

Зарубежные микросхемы, транзисторы, диоды

0...9

новейший справочник

Наука и Техника

ЗАРУБЕЖНЫЕ
микросхемы транзисторы диоды

0...9

Наука и Техника
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Зарубежные микросхемы, транзисторы, диоды. 0...9

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Серия «Электронные компоненты»

В настоящее время очень хорошо прослеживается динамика развития ведущих производителей электронных полупроводниковых приборов США, Японии и Западной Европы. Совсем недавно достаточно громко заявила о себе Южная Корея, в основном благодаря научно-техническому прогрессу фирмы SAMSUNG.

В связи с тем, что в странах бывшего СССР появилось огромное количество разнообразной электронной аппаратуры зарубежного производства, возникла необходимость в создании подобного справочника, охватывающего почти всю гамму зарубежных полупроводниковых приборов.

При составлении справочника использовалась техническая документация 1999-2000 г.г. некоторых фирм-производителей электронных полупроводниковых приборов, систематизирована информация, взятая из нескольких справочников, изданных в Европе и самого популярного в США справочника «ECG Semiconductor Master Replacement Guide» 1998 г. Иногда составителю встречались некоторые расхождения между характеристиками электронных полупроводниковых приборов, описанных в справочниках, изданных в Европе и в технической документации фирм-производителей. Подобные расхождения были откорректированы.

Справочник предназначен в первую очередь для инженерно-технического персонала, занимающегося сервисным обслуживанием зарубежного электронного оборудования и, надеемся, будет также полезен радиолюбителям.

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СОДЕРЖАНИЕ

Информация для пользователя

В справочнике в алфавитном порядке представлен наиболее полный перечень (ок. 80000) электронных полупроводниковых приборов, включая появившиеся на рынке в 2000 г., а также микросхемы ТТЛ, логику на МОП-структуре и стабилизаторы напряжения в интегральном исполнении.

Для каждого прибора приведены основные электрические параметры, особенности и область их применения. Для большинства приборов приведен ряд их наиболее распространенных аналогов.

Промышленные стандарты и системы обозначений электронных полупроводниковых приборов США, Японии и Европы, помещенные в справочнике, помогут вам классифицировать любой вышедший из строя полупроводниковый прибор и найти с помощью нашего справочника ему замену. Объем справочника не позволяет привести полностью электрические параметры для каждого электронного полупроводникового прибора. В случае недостаточности информации о характеристиках интересующего вас прибора целесообразно обратиться к документации фирм-производителей, на сайтах которых помещено большое количество справочной информации. Ряд WEB-адресов производителей приведен в конце справочника.

Промышленные стандарты и системы обозначения полупроводниковых приборов

Стандарт США EIA-JEDEC — Electronic Industries Accosiation

Согласно этого стандарта электронные полупроводниковые приборы обозначаются кодом (маркировкой), в котором *первая цифра* соответствует количеству p-n-переходов:

1 .... диоды
2 .... транзисторы
3 .... тиристоры

за цифрой следует буква N и серийный номер прибора.

Европейская система PRO ELECTRON — International Pro Electron

Согласно этой системы электронные полупроводниковые приборы обозначаются следующим образом:

Первая буква — материал, из которого изготовлен прибор:

A .... германий
B .... кремний
C .... арсенид галлия
D .... антимонид индия
R .... химическое соединение (например, сульфид кадмия)

Вторая буква соответствует подклассу прибора и показывает функциональные особенности:

A .... диоды детекторные, быстродействующие, смесительные
B .... диоды с переменной емкостью
C .... транзисторы НЧ, маломощные
D .... транзисторы НЧ, мощные
E .... диоды туннельные
F .... транзисторы ВЧ, маломощные
L .... транзисторы ВЧ, мощные
S .... транзисторы переключающие, маломощные
U .... транзисторы переключающие, мощные

После букв следует двухзначный, трехзначный или четырехзначный номер. Буква, стоящая после номера, указывает на отличительные параметры (например, пробивное напряжение, усиление, напряжение насыщения, форма корпуса и т.д.).

Японский стандарт JIS

Японский промышленный стандарт создан на базе систем JEDEC и Pro-Etectron. Согласно этого стандарта условное обозначение электронного полупроводникового прибора состоит из четырех элементов.

I-й элемент:

0 .... фотодиод, фототранзистор
1 .... диод
2 .... транзистор
3 .... четырехслойный прибор

II-й элемент указывает на принадлежность к классу электронных полупроводниковых приборов и обозначается буквой S.

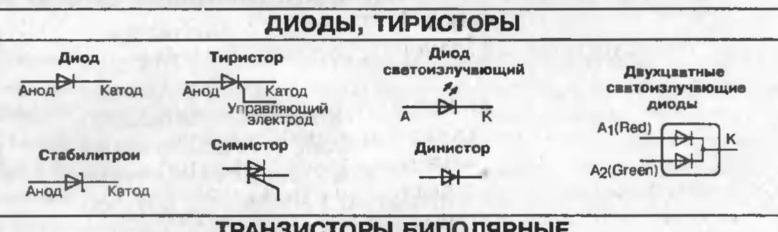
III-й элемент:

A .... транзистор p-n-p ВЧ
B .... транзистор p-n-p НЧ
C .... транзистор n-p-n ВЧ
D .... транзистор n-p-n НЧ
E .... диод Есаки
F .... тиристор
G .... диод Гана
H .... однопереходной транзистор
J .... полевой транзистор с p-каналом
K .... полевой транзистор с n-каналом
M .... симметричный тиристор
R .... выпрямительный диод
S .... малосигнальный диод
T .... лавинный диод
V .... pin-диод
Z .... стабилитрон

IV-й элемент — серийный номер.

Графические обозначения электронных полупроводниковых приборов

ДИОДЫ, ТИРИСТОРЫ



ТРАНЗИСТОРЫ БИПОЛЯРНЫЕ



ТРАНЗИСТОРЫ ПОЛЕВЫЕ

D .... сток (Drain)
S .... исток (Sourse)
G .... затвор (Gate)
B .... подложка (Substrate)
C .... корпус (Case)

"n" - канальный полевой транзистор

"p" - канальный полевой транзистор

Трехвыводной МДП (MOS) транзистор с встроенным n-каналом

Трехвыводной МДП (MOS) транзистор с встроенным p-каналом

Четырехвыводной МДП (MOS) транзистор с встроенным n-каналом

Четырехвыводной МДП (MOS) транзистор с встроенным p-каналом

Трехвыводной МДП (MOS) транзистор с индуцированным n-каналом

Трехвыводной МДП (MOS) транзистор с индуцированным p-каналом

Четырехвыводной МДП (MOS) транзистор с индуцированным n-каналом

Четырехвыводной МДП (MOS) транзистор с встроенным p-каналом

Двухзатворный МДП (MOS) транзистор с встроенным каналом

Двухзатворный МДП (MOS) транзистор с индуцированным каналом

МДП транзистор с индуцированным n-каналом и защитным диодом

МДП транзистор с индуцированным n-каналом и стабилитроном

МДП транзистор с индуцированным n-каналом и управлением по току

Краткие пояснения к таблице «Параметры электронных полупроводниковых приборов и микросхем»

ТИП (Колонка 1)

В колонке приводится фирменное обозначение элемента, соответствующее документации изготовителя, которое в полной или сокращенной форме наносится на корпус прибора. Старые фирменные названия полупроводниковых элементов сохранены без изменений.

СТРУКТУРА (Колонка 2)

В колонке приводится краткое описание полупроводниковых приборов, их структура и принадлежность к одному из подклассов (диод, транзистор и т.д.).

Используемые сокращения:

C-Di .... диод с изменяемой емкостью p-n перехода (варикап)
CMOS-IC ..... микросхема на комплементарных МОП-транзисторах
CMOS-Logic . логика на комплементарных МОП-транзисторах
Diac .... симметричный диодный тиристор, симметричный динистор
EEPROM-IC...ПЗУ
FET .... полевой транзистор
F-Thy .... запираемый тиристор
F-Thy+Di ..... тиристор для TV строчной развертки
GaAs .... арсенид галлия
Ge-Di .... германиевый диод
Ge-N .... германиевый n-p-n транзистор
Ge-P .... германиевый p-n-p транзистор
GTO-Thy ...... двухоперационный диодный тиристор, двухопер. тринистор
Hybrid-Z-IC . ГИС
MOS .... металл-оксид-кремний, металл-оксид-полупроводник (МОП-структура)
MOS-FET-d . полевой МОП-транзистор со встроенным каналом
MOS-FET-e . полевой МОП-транзистор с индуцированным каналом
MOS-N-FET . МОП-структура с n-каналом
N-FET .... полевой транзистор с n-каналом
Opto .... оптоэлектронный компонент
PIN-Di .... pin-диод
PUT .... программируемый однопереходной транзистор
P-FET .... полевой транзистор с p-каналом
Ref-Di .... выпрямительный диод
SAW-Filter ... фильтр на поверхностных акустических волнах
SBS .... система коммерческой спутниковой связи
Se-Di .... селеновый диод

Si-Br .... кремниевый мостовой выпрямитель
Si-Di .... кремниевый диод
Si-N .... кремниевый n-p-n транзистор
Si-N-Darl ..... кремниевый n-p-n транзистор Дарлингтона
Si-P .... кремниевый p-n-p транзистор
Si-P-Darl ...... кремниевый p-n-p транзистор Дарлингтона
Si-St .... кремниевый, со стабильными параметрами
SUS .... кремниевый однонаправленный переключатель
Tetrode .... тетрод
Thy .... тиристор
Thy-Br .... тиристорный шунт (мостовой)
Triac .... симистор
Trigger-Di ..... триггер-диод
TTL-Logic..... ТТЛ
UJT .... однопереходной транзистор, двухбазовый диод
Z-Di .... диод Зенера (стабилитрон)
Z-IC .... стабилизатор наряжения в интегральном исполнении
...+Di .... элемент со встроенным диодом
...+R .... элемент со встроенным резистором
50Hz-Thy ..... сетевой (магистральный) тиристор
...-d .... режим обеднения
...-e .... режим обогащения
...d/e .... режим обеднения/обогащения

ХАРАКТЕРИСТИКИ (Колонка 3)

В колонке приводятся область применения и краткие технические данные электронных полупроводниковых приборов и микросхем.

Используемые сокращения:

A .... антенные широкополосные усилители
AFC .... автоматическая подстройка частоты (АПЧ)
AFT .... автоматическая точная настройка
AGC .... автоматическая регулировка усиления (АРУ)
ALC .... автоматическая регулировка уровня сигнала
AM .... амплитудная модуляция
AMP .... усилитель
APC .... автоматическая подстройка фазы (АПФ)
ARI .... системы коммутации
Array .... матрица, элементы в одном корпусе
Asym .... асимметричный
A/W-Verst .... универсальный усилитель
B .... коэффициент усиления по току
Band-s .... радиочастотный переключатель диапазона
Bi-direktional ..... двунаправленный
Br .... мост
Btx .... телетекст
CATV .... кабельное телевидение
CB .... полоса частот, отведенная для служебной радиосвязи
Chopper .... прерыватель

ContrAv .... лавинно-управляемый
Chroma .... цветность, насыщенность
CRT .... электронно-лучевая трубка
CTV .... цветное телевидение
Dem .... демодуляторные каскады
Diskr .... дискриминаторы
Dual .... двойной (пара элементов в одном корпусе)
E .... выходные каскады
Equal .... эквалайзер
FB .... дистанционное управление
FED .... полевой диод
FM .... частотная модуляция
F/V-Convertor .... преобразователь частота/напряжение
Gep .... согласованные
GL .... выпрямитель
Gunn-Di .... диод Ганна
TV-HA .... ТВ, каскады строчной развертки
HF .... высокая частота
Hi-beta .... с большим коэффициентом усиления по току
Hi-current .... с большим выходным током
Hi-def .... с большой четкостью изображения
Hi-power .... с большой выходной мощностью
Hi-prec .... высокоточные
Hi-rel .... высоконадежные
Hi-res .... с высоким разрешением
Hi-speed .... быстродействующие
Hi-volt .... высоковольтные
Horiz .... горизонтальный (строчный)
Hi-ohm .... высокоомные
Ib .... ток базы
If .... промежуточная частота
Igt .... импульсный ток
Ih .... ток удержания
Ivpath-Di .... лавинный диод
Indic .... индикатор
IR .... инфракрасное излучение
Ip .... пиковый ток
Is .... ток переключения
Iso .... ток утечки
Kl .... ТВ, демпферный диод
KV-GL .... высоковольтные цепи (выпрямитель)
L .... мощные каскады
HV .... высоковольтный
Mot. Tr .... схемы управления моторами
LCD .... жидкокристаллический индикатор
LED .... светоизлучаюший диод
Limiter .... ограничитель
Logl .... низкий логический уровень
Lo-noise .... малошумящие

Lo-power ...... малой мощности
Lo-Sat .... с низким напряжением насыщения
Lo-volt .... низковольтные
M .... смесительные каскады
Min .... минимальные значения
Mix .... смеситель
n-ohm .... низкоимпедансные цепи
O .... генераторные каскады
OP-Amp .... операционный усилитель
Osc .... генератор
Par .... параллельно
PEP .... пиковое значение мощности огибающей
PLL .... фазовая автоподстройка частоты (ФАПЧ)
PQ .... выходная мощность транзистора (передатчика)
Progr .... программируемый
PS .... источник питания
PWM .... широтно-импульсная модуляция
ra .... малошумящие
Reg .... стабилизатор, регулятор
S .... переключающие каскады
Schottky .... эффект Шоттки
Ser .... последовательный
SMD .... прибор для поверхностного монтажа
SMPS .... импульсный источник питания
SS .... быстропереключающие каскады
SSB .... с одной боковой полосой
Stack .... выпрямительные столбы
Sym .... симметричные
TAZ .... демпферный диод
tgg .... разовый сброс
Thy-Br .... тиристор мостовой конфигурации
Ton .... звуковой канал (телевидение)
Tr .... задающие каскады
Trigger-Di ..... четырехслойный триггер-диод асимметричный
tuning .... радиочастотный перестраиваемый
Tunnel-Di ..... туннельный диод
TV .... телевидение
TV-VA .... ТВ, каскады кадровой развертки
UART .... универсальный асинхронный приемопередатчик
Ub .... напряжение базы
Ucc .... напряжение питания
UHF .... дециметровый диапазон
Uni .... универсальный
US .... ультразвук
USART .... универсальный синхронно-асинхронный приемопередатчик
V .... каскады предварительного входа
VC .... видеомагнитофон
Vertic .... вертикальный, кадровый
VHF .... диапазон метровых волн

Vd .... выходные видеокаскады
W .... коррекция цвета
Vtx .... телетекст
V/F-convertor .... преобразователь напряжение/частота
X-Ray-prot .... защищенный от рентгеновского излучения
B .... коэффициент усиления по току
Eff........................ эффективное значение
ss .... пиковая максимальная величина
(Ta=...) .... температура окружающей среды
(Tc=...) .... температура корпуса
=(Typ) .... соответствует типу, но отличается по параметрам
-/...V .... при известном значении коллектор-эмиттер, но других значениях параметров
...ns .... время восстановления (диоды)
.../-ns .... время включения (транзисторы)
../.ns.................... время переключения (транзисторы)
...ms .... время выключения (тиристоры)
...+Diac .... с интегрированным элементом

VLF .... диапазон частот 3...30 кГц (ОНЧ)
LF .... диапазон частот 30...300 кГц (НЧ)
MF .... диапазон частот 300...3000 кГц (СЧ)
NF .... диапазон частот 3...30 МГц (ВЧ)
VHF .... диапазон частот 30...300 МГц (ОВЧ)
UHF .... диапазон частот 300...3000 МГц (УВЧ)
SHF .... диапазон частот 3...30 ГГц (СВЧ)
EHF .... диапазон частот 30...300 ГГц (КВЧ)

КОРПУС (Колонка 4)

В колонке приведены номера рисунков корпусов полупроводниковых приборов. Маленькая буква после номера рисунка обозначает вариант расположения выводов для полупроводниковых приборов различных классов. Эти варианты приведены в таблицах pin-кодов (стр. 672), где даны условные обозначения выводов. Например, для транзисторов вариант b дает: 1 вывод — эмиттер (E), 2 вывод — коллектор (C), 3 вывод — база (B). Большая буква указывает на вариант схемы для составных транзисторов Дарлингтона.

ПРОИЗВОДИТЕЛЬ (Колонка 5)

В колонке даны сокращенные названия фирм-производителей. Полные названия производителей помещены в таблице на стр. 673.

АНАЛОГИ (Колонка 6)

В колонке приводятся аналоги электронных полупроводниковых приборов наиболее близкие по своим характеристикам к исходному типу. Приведенные аналоги не исключают возможности альтернативного поиска замены, а лишь носят рекомендательный характер. Решение о замене ос-

тается за пользователем и определяется конкретными условиями. Полупроводниковые приборы, имеющие неполное соответствие, заключены в скобки с индексом ()**, где индекс обозначает:

1 ...... с интегрированным демпферным диодом
2 ...... с демпферным диодом между эмиттером и коллектором
3 ...... с неизолированным корпусом
4 ...... с различием в корпусах
5 ...... отличия в выводах
6 ...... альтернативных типов намного больше
7 ...... альтернативные типы с более низкими максимальными параметрами
8 ...... с более низкими граничными частотами
9 ...... с наличием других вентилей
10 .... несовместимы по выводам или другое их расположение
11 .... с различием в корпусах
12 .... с температурными различиями
13 .... с меньшим коэффициентом усиления по току
14 .... отличие в параметрах
15 .... с демпферным диодом и с отличием по выводам
16 .... с ограниченным диапазоном температур
17 .... с более высоким напряжением насыщения
18 .... с подбором внешних резисторов
+ ..... множество дополнительных вариантов замены.

Элементы с нестандартными обозначениями

(2)GA 109	Ge-Di	FM-Dem, 50V, 0,015A	31a	Hfo	AA 113, 1N34, 1N54, 1N60
(2)GA 113	Ge-Di	Dem, Diskr, 35V, 0,03A(ss)	31a	Hfo	AA 113, AA 119, 1N34, 1N54, 1N60
(2)OA646	Ge-Di	=GA 109	31a	Hfo	→GA 109
(4)GA 114	Ge-Di	4x Ge-Di, Ring-Dem, 35V, 0,03A(ss)	31a	Hfo	→4x GA 113
(AEG) 1006		1600/1700V, 2,3mA	31a		E800C2,3
(AEG) 896	Se-Di	880/950V, 3,3mA	31a		E400C3,3
(AEG) 972	Se-Di	1100/1200V, 3mA	31a		E500C3
(AEG) 992	Se-Di	1300/1450V, 2,7mA	31a		E600C2,7
(NT)0100(ECO)	Si-Di	Uni, 75V, 0,125A	2c	Ntn	BA 157..159, BAY 19..21, BAY 87..89, ++
(NT)0101(ECO)	Si-Di	=(NT)0100(ECO): 150V	2c	Ntn	BA 157..159, BAY 20..21, BAY 88..89, ++
(NT)0102(ECO)	Si-Di	=(NT)0100(ECO): 300V	2c	Ntn	BA 157..159, BAY 21, BAY 88..89, ++
(NT)0110(ECO)	Si-Di	=(NT)0100(ECO)	2c	Ntn	BA 157..159, BAY 19..21, BAY 87..89, ++
(NT)0111(ECO)	Si-Di	=(NT)0100(ECO): 150V	2c	Ntn	BA 157..159, BAY 20..21, BAY 88..89, ++
(NT)0112(ECO)	Si-Di	=(NT)0100(ECO): 300V	2c	Ntn	BA 157..159, BAY 21, BAY 88..89, ++
(NT)0114(ECO)	Si-Di	=(NT)0100(ECO): 500V	2c	Ntn	BA 158..159, BA 199/550, BAY 89..91, ++
(NT)0241(ECO)	Si-Di	GI-L, 100V, 3A(Tc=100°)	32b	Ntn	BYX 38/300R, BYX 39/600R
(NT)0241..48R(ECO)	Si-Di	=(NT)0241..0248(ECO): 800V	32a		BYX 38/.., BYX 39/..
(NT)0242(ECO)	Si-Di	=(NT)0241(ECO): 200V	32b		BYX 38/300R, BYX 39/600R
(NT)0243(ECO)	Si-Di	=(NT)0241(ECO): 300V	32b		BYX 38/300R, BYX 39/600R
(NT)0245(ECO)	Si-Di	=(NT)0241(ECO): 500V	32b		BYX 38/600R, BYX 39/600R
(NT)0248(ECO)	Si-Di	=(NT)0241(ECO): 800V	32b		BYX 38/900R, BYX 39/800R
(NT)0300(ECO)	Si-Di	GI, 75V, 0,75A	31a	Ntn	BY 126..127, BY 133..135, 1N4002..07, ++
(NT)0301(ECO)	Si-Di	=(NT)0300(ECO): 150V	31a		BY 126..127, BY 133..135, 1N4003..07, ++
(NT)0302(ECO)	Si-Di	=(NT)0300(ECO): 300V	31a		BY 126..127, BY 133..134, 1N4004..07, ++
(NT)0304(ECO)	Si-Di	=(NT)0300(ECO): 500V	31a		BY 126..127, BY 133..134, 1N4005..07, ++
(NT)0307(ECO)	Si-Di	=(NT)0300(ECO): 800V	31a		BY 127, BY 133, BY 227, 1N4006..07, ++
(NT)0310(ECO)	Si-Di	=(NT)0300(ECO)	31a		BY 126..127, BY 133..135, 1N4002..07, ++
(NT)0311(ECO)	Si-Di	=(NT)0300(ECO): 150V	31a		BY 126..127, BY 133..135, 1N4003..07, ++
(NT)0312(ECO)	Si-Di	=(NT)0300(ECO): 300V	31a		BY 126..127, BY 133..134, 1N4004..07, ++
(NT)0314(ECO)	Si-Di	=(NT)0300(ECO): 500V	31a		BY 128..127, BY 133..134, 1N4005..07, ++
(NT)0317(ECO)	Si-Di	=(NT)0300(ECO): 800V	31a		BY 127, BY 133, BY 227, 1N4006..07, ++
(NT)0320(ECO)	Si-Di	=(NT)0300(ECO)	31a		BY 126..127, BY 133..135, 1N4002..07, ++
(NT)0321(ECO)	Si-Di	=(NT)0300(ECO): 150V	31a		BY 126..127, BY 133..135, 1N4003..07, ++
(NT)0322(ECO)	Si-Di	=(NT)0300(ECO): 300V	31a		BY 126..127, BY 133..134, 1N4004..07, ++
(NT)0324(ECO)	Si-Di	=(NT)0300(ECO): 500V	31a		BY 126..127, BY 133..134, 1N4005..07, ++
(NT)0327(ECO)	Si-Di	=(NT)0300(ECO): 800V	31a		BY 127, BY 133, BY 227, 1N4006..07, ++
(NT)0400(ECO)	Si-Di	Uni, 75V, 0,25A	31a	Ntn	BA 157..159, BA 199/250, BAY 19..21, ++
(NT)0401(ECO)	Si-Di	=(NT)0400(ECO): 150V	31a		BA 157..159, BA 199/250, BAY 20..21, ++
(NT)0402(ECO)	Si-Di	=(NT)0400(ECO): 300V	31a		BA 157..159, BA 199/350, BAY 21, ++
(NT)0404(ECO)	Si-Di	=(NT)0400(ECO): 500V	31a		BA 158..159, BA 199/550, BAY 89..91, ++
(NT)0410(ECO)	Si-Di	=(NT)0400(ECO)	31a	Ntn	BA 157..159, BA 199/250, BAY 19..21, ++
(NT)0411(ECO)	Si-Di	=(NT)0400(ECO): 150V	31a	Ntn	BA 157..159, BA 199/250, BAY 20..21, ++
(NT)0412(ECO)	Si-Di	=(NT)0400(ECO): 300V	31a	Ntn	BA 157..159, BA 199/350, BAY 21, ++
(NT)0414(ECO)	Si-Di	=(NT)0400(ECO): 500V	31a	Ntn	BA 158..159, BA 199/550, BAY 89..91, ++
(NT)0500(ECO)	Si-Di	Uni, 75V, 0,25A	31a	Ntn	BA 157..159, BA 199/250, BAY 19..21, ++
(NT)0501(ECO)	Si-Di	=(NT)0500(ECO): 150V	31a		BA 157..159, BA 199/250, BAY 20..21, ++
(NT)0502(ECO)	Si-Di	=(NT)0500(ECO): 300V	31a		BA 157..159, BA 199/350, BAY 21, ++
(NT)0503(ECO)	Si-Di	=(NT)0500(ECO): 400V	31a		BA 157..159, BA 199/550, BAY 89..91, ++
(NT)0504(ECO)	Si-Di	=(NT)0500(ECO): 500V	31a		BA 158..159, BA 199/550, BAY 89..91, ++
(NT)0507(ECO)	Si-Di	=(NT)0500(ECO): 800V	31a	Ntn	BA 159, BAY 90..91, BY 204/8, ++
(NT)0601(ECO)	Si-Di	GI-L, 200V, 17,5A(Tc=100°)	32b	Ntn	BYX 25/600R, SSiE2040
(NT)0601..08R(ECO)	Si-Di	=(NT)0601..0608(ECO):	32a		BYX 25/..
(NT)0602(ECO)	Si-Di	=(NT)0601(ECO): 300V	32b		BYX 25/600R, SSiE2040
(NT)0604(ECO)	Si-Di	=(NT)0601(ECO): 800V	32b		BYX 25/600R, SSiE2040
(NT)0606(ECO)	Si-Di	=(NT)0601(ECO): 900V	32b		BYX 25/1000R, SSiE2060
(NT)0608(ECO)	Si-Di	=(NT)0601(ECO): 1200V	32b		BYX 25/1200R, SSiE2080
(NT)0612(ECO)	Si-Di	GI-L, 300V, 40A(Tc=100°)	73b	Ntn	D60/400, DS 42-04A
(NT)0614(ECO)	Si-Di	=(NT)0612(ECO): 800V	73b		D60/800, DS 42-07A
(NT)0616(ECO)	Si-Di	=(NT)0812(ECO): 900V	73b		D60/1200, DS42-11A
(NT)0618(ECO)	Si-Di	=(NT)0612(ECO): 1200V	73b		D60/1200, DS 42-14A
(NT)0619(ECO)	Si-Di	-(NT)0612(ECO): 1500V	73b		D60/1800, DS 42-16A
(NT)0622(ECO)	Si-Di	GI-L, 300V, 100A(Tc=100°)	73b	Ntn	D160/400, DS85-04C
(NT)0624(ECO)	Si-Di	=(NT)0622(ECO): 600V	73b		D160/800, DS85-06C

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(NT)0626(ECO)	Si-Di	=(NT)0622(ECO): 900V	73b		D160/1200, DS65-10C
(NT)0628(ECO)	Si-Di	=(NT)0622(ECO): 1200V	73b		D160/1200, DS85-12C
(NT)0629(ECO)	Si-Di	=(NT)0622(ECO): 1500V	73b		D160/1600, DS65-16C
(NT)0632(ECO)	Si-Di	Gl-L, 300V, 20A(Tc=100°)	73b	Ntn	D21S/1000, D24/400
(NT)0634(ECO)	Si-Di	=(NT)0632(ECO): 600V	73b		D21S/1000, D24/600
(NT)0636(ECO)	Si-Di	=(NT)0632(ECO). 900V	73b		D21S/1000, D24/1200
(NT)0636(ECO)	Si-Di	=(NT)0632(ECO): 1200V	73b	Ntn	D21S/1200, D24/1200
(NT)0639(ECO)	Si-Di	=(NT)0632(ECO): 1500V	73b	Ntn	D24/1600
(NT)0700(ECO)	Si-Di	≈1N4002	31a	Ntn	→1N4002
(NT)0701(ECO)	Si-Di	≈1N4003	31a		→1N4003
(NT)0702(ECO)	Si-Di	≈1N4004	31a		→1N4004
(NT)0704(ECO)	Si-Di	≈1N4005	31a	Ntn	→1N4005
(NT)0707(ECO)	Si-Di	≈1N4006	31a		→1N4006
(NT)0708(ECO)	Si-Di	≈1N4007	31a		→1N4007
(NT)0710(ECO)	Si-Di	≈1N4001	31a		→1N4001
(NT)0771(ECO)	Si-Di	Gl, Uni, 150V, 1,5A	31a	Ntn	BY226. 227, BY251..255, 1N5393..99,++
(NT)0772(ECO)	Si-Di	=(NT)0771(ECO): 300V	31a		BY226..227, BY252. 255, 1N5394 99,++
(NT)0774(ECO)	Si-Di	=(NT)0771(ECO): 500V	31a		BY226. 227, BY253..255, 1N5397..99,++
(NT)0776(ECO)	Si-Di	=(NT)0771(ECO): 600V	31a		BY227, BY254..255, 1N5398..99,++
(NT)0776(ECO)	Si-Di	=(NT)0771(ECO): 1000V	31a		BY227, BY226, BY255, 1N5399,++
(NT)0779(ECO)	Si-Di	=(NT)0771(ECO): 1200V	31a		BY227, BY228, BY255, BYX67, ++
(NT)0952(ECO)	Si-Di	kV-Gl, 1kV, 0,6A		Ntn	—
(NT)0953(ECO)	Si-Di	=(NT)0952(ECO): 1,5kV			—
(NT)0954(ECO)	Si-Di	=(NT)0952(ECO): 2kV			—
(NT)0955(ECO)	Si-Di	=(NT)0952(ECO): 2,5kV			—
(NT)0956(ECO)	Si-Di	=(NT)0952(ECO): 3kV			—
(NT)0957(ECO)	Si-Di	=(NT)0952(ECO): 3,5kV			—
(NT)0956(ECO)	Si-Di	=(NT)0952(ECO). 4kV			—
(NT)1005..33(ECO)	Z-Di	→(NT)1105..1133(ECO)		Ntn	—
(NT)1101(c)(ECO)	Z-Di	2,7V, 0,25W, 10%(β=5%)	2c	Ntn	BZX55/.., BZX79/.., ZPD.., 1N4682..4714+
(NT)1102(c)(ECO)	Z-Di	=(NT)1101(c)(ECO) 3,3V	2c		—
(NT)1103(c)(ECO)	Z-Di	=(NT)1101(c)(ECO): 3,9V	2c		—
(NT)1104(c)(ECO)	Z-Di	=(NT)1101(c)(ECO): 4,7V	2c		—
(NT)1105(c)(ECO)	Z-Di	=(NT)1101(c)(ECO) 5,6V	2c		—
(NT)1106(c)(ECO)	Z-Di	=(NT)1101(c)(ECO): 6,8V	2c		—
(NT)1107(c)(ECO)	Z-Di	=(NT)1101(c)(ECO): 7,5V	2c		—
(NT)1106(c)(ECO)	Z-Di	=(NT)1101(c)(ECO): 8,2V	2c		—
(NT)1109(c)(ECO)	Z-Di	=(NT)1101(c)(ECO): 9,1V	2c		—
(NT)1110(c)(ECO)	Z-Di	=(NT)1101(c)(ECO): 10V	2c		—
(NT)1111(c)(ECO)	Z-Di	=(NT)1101(c)(ECO): 11V	2c		—
(NT)1112(c)(ECO)	Z-Di	=(NT)1101(c)(ECO) 12V	2c		—
(NT)1113(c)(ECO)	Z-Di	=(NT)1101(c)(ECO): 13V	2c		—
(NT)1115(c)(ECO)	Z-Di	=(NT)1101(c)(ECO): 15V	2c		—
(NT)1116(c)(ECO)	Z-Di	=(NT)1101(c)(ECO): 16V	2c		—
(NT)1118(c)(ECO)	Z-Di	=(NT)1101(c)(ECO). 18V	2c		—
(NT)1120(c)(ECO)	Z-Di	=(NT)1101(c)(ECO): 20V	2c		—
(NT)1122(c)(ECO)	Z-Di	=(NT)1101(c)(ECO): 22V	2c		—
(NT)1124(c)(ECO)	Z-Di	=(NT)1101(c)(ECO): 24V	2c		—
(NT)1127(c)(ECO)	Z-Di	=(NT)1101(c)(ECO). 27V	2c		—
(NT)1130(c)(ECO)	Z-Di	=(NT)1101(c)(ECO): 30V	2c		—
(NT)1133(c)(ECO)	Z-Di	=(NT)1101(c)(ECO): 33V	2c		—
(NT)1203(c)(ECO)	Z-Di	3,9V, 15W(Tc=45°), 10%(c=5%)	32a	Ntn	BZX98/... BZY93/..
(NT)1204(c)(ECO)	Z-Di	=(NT)1203(c)(ECO) 4,7V	32a		—
(NT)1205(c)(ECO)	Z-Di	=(NT)1203(c)(ECO): 5,6V	32a		—
(NT)1206(c)(ECO)	Z-Di	=(NT)1203(c)(ECO): 6,8V	32a		—
(NT)1207(c)(ECO)	Z-Di	=(NT)1203(c)(ECO): 7,5V	32a		—
(NT)1208(c)(ECO)	Z-Di	=(NT)1203(c)(ECO): 8,2V	32a		—
(NT)1209(c)(ECO)	Z-Di	=(NT)1203(c)(ECO): 9,1V	32a		—
(NT)1210(c)(ECO)	Z-Di	=(NT)1203(c)(ECO): 10V	32a		—
(NT)1211(c)(ECO)	Z-Di	=(NT)1203(c)(ECO): 11V	32a		—
(NT)1212(c)(ECO)	Z-Di	=(NT)1203(c)(ECO): 12V	32a		—
(NT)1213(c)(ECO)	Z-Di	=(NT)1203(c)(ECO): 13V	32a		—
(NT)1301(c)(ECO)	Z-Di	2,7V, 1W, 10%(c=5%)	31a	Ntn	BZW22/.., BZX61/.., ZPY.., 1N4723..4743+
(NT)1302(c)(ECO)	Z-Di	=(NT)1301(c)(ECO): 3,3V	31a		—
(NT)1303(c)(ECO)	Z-Di	=(NT)1301(c)(ECO): 3,9V	31a		—
(NT)1304(c)(ECO)	Z-Di	=(NT)1301(c)(ECO): 4,7V	31a		—

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(NT)1305(c)(ECO)	Z-Di	=(NT)1301(c)(ECO): 5,6V	31a		—
(NT)1306(c)(ECO)	Z-Di	=(NT)1301(c)(ECO): 6,8V	31a		—
(NT)1307(c)(ECO)	Z-Di	=(NT)1301(c)(ECO): 7,5V	31a		—
(NT)1306(c)(ECO)	Z-Di	=(NT)1301(c)(ECO): 8,2V	31a		—
(NT)1309(c)(ECO)	Z-Di	=(NT)1301(c)(ECO): 9,1V	31a		—
(NT)1310(c)(ECO)	Z-Di	=(NT)1301(c)(ECO): 10V	31a		—
(NT)1311(c)(ECO)	Z-Di	=(NT)1301(c)(ECO): 11V	31a		—
(NT)1312(c)(ECO)	Z-Di	=(NT)1301(c)(ECO): 12V	31a		—
(NT)1313(c)(ECO)	Z-Di	=(NT)1301(c)(ECO): 13V	31a		—
(NT)1315(c)(ECO)	Z-Di	→(NT)5324(c)(ECO)	31a		—
(NT)1316(c)(ECO)	Z-Di	→(NT)5325(c)(ECO)	31a		—
(NT)1318(c)(ECO)	Z-Di	→(NT)5326(c)(ECO)	31a		—
(NT)1320(c)(ECO)	Z-Di	→(NT)5327(c)(ECO)	31a		—
(NT)1322(c)(ECO)	Z-Di	→(NT)5326(c)(ECO)	31a		—
(NT)1324(c)(ECO)	Z-Di	→(NT)5329(c)(ECO)	31a		—
(NT)1327(c)(ECO)	Z-Di	→(NT)5330(c)(ECO)	31a		—
(NT)1330(c)(ECO)	Z-Di	→(NT)5331(c)(ECO)	31a		—
(NT)1333(c)(ECO)	Z-Di	→(NT)5332(c)(ECO)	31a		—
(NT)1336(c)(ECO)	Z-Di	→(NT)5333(c)(ECO)	31a		—
(NT)1339(c)(ECO)	Z-Di	→(NT)5334(c)(ECO)	31a		—
(NT)1343(c)(ECO)	Z-Di	→(NT)5335(c)(ECO)	31a		—
(NT)1347(c)(ECO)	Z-Di	→(NT)5336(c)(ECO)	31a		—
(NT)1405(ECO)	Z-Di	→(NT)1305(ECO)	31a	Ntn	—
(NT)1406(ECO)	Z-Di	→(NT)1306(ECO)	31a		—
(NT)1408(ECO)	Z-Di	→(NT)1308(ECO)	31a		—
(NT)1410(ECO)	Z-Di	→(NT)1310(ECO)	31a		—
(NT)1412(ECO)	Z-Di	→(NT)1312(ECO)	31a		—
(NT)1415(ECO)	Z-Di	→(NT)5324(ECO)	31a		—
(NT)1418(ECO)	Z-Di	→(NT)5326(ECO)	31a		—
(NT)1422(ECO)	Z-Di	→(NT)5328(ECO)	31a		—
(NT)1427(ECO)	Z-Di	→(NT)5330(ECO)	31a		—
(NT)1433(ECO)	Z-Di	→(NT)5332(ECO)	31a		—
(NT)1439(ECO)	Z-Di	→(NT)5334(ECO)	31a		—
(NT)1447(ECO)	Z-Di	→(NT)5336(ECO)	31a		—
(NT)2301(ECO)	Si-Di	Uni, S, 220V, 0,05A, 1,5µs	31a	Ntn	BA 147/230, BAY 21, BAY 46, 1N5196, ++
(NT)2302(ECO)	Si-Di	=(NT)2301(ECO):	31a		BA 147/230, BAY 21, BAY 46, 1N5196, ++
(NT)2303(ECO)	Si-Di	=(NT)2301(ECO): 100V, 0,5A	31a		BA 157..159, BA193..194, BY 402..405, ++
(NT)2304(ECO)	Si-Di	=(NT)2301(ECO): 50V	31a		BA 147/50, BAY 18..21, 1N5194..96, ++
(NT)2401(ECO)	Si-Di	Uni, S, 25V, 0,1A, <2,5µs	31a	Ntn	BA 147/50, BAY 18..21, 1N5194..98, ++
(NT)2403(ECO)	Si-Di	=(NT)2401(ECO): 55V	31a		BA 147/50, BAY 18..21, 1N5194..96, ++
(NT)2405(ECO)	Si-Di	=(NT)2401(ECO): 80V	31a		BA 147/100, BAY 19..21, 1N5195..98, ++
(NT)2410(ECO)	Si-Di	=(NT)2401(ECO): 150V	31a		BA 147/150, BAY 20..21, 1N5195..96, ++
(NT)2415(ECO)	Si-Di	=(NT)2401(ECO): 200V	31a		BA 147/230, BAY 21, 1N5195..96, ++
(NT)2420(ECO)	Si-Di	=(NT)2401(ECO): 250V	31a		BA 147/300, BAY 21, BAY 46, 1N5196, ++
(NT)2502(ECO)	Si-Di	Gl, S, 200V, 0,6A, 5µs	31a	Ntn	BY 126..127, BY 133..134, 1N4003..07, ++
(NT)2504(ECO)	Si-Di	=(NT)2502(ECO): 400V	31a		BY 128..127, BY 133..134, 1N4004..07, ++
(NT)2506(ECO)	Si-Di	=(NT)2502(ECO): 600V	31a		BY 126..127, BY 133..134, 1N4005..07, ++
(NT)2602(ECO)	Si-Di	Gl/S-L, 200V, 3A(Tc=100°)	32b	Ntn	BYX 38/300R, BYX 39/600R
(NT)2602..08R(ECO)	Si-Di	=(NT)2602(ECO):	32a		BYX 38/.., BYX 39/..
(NT)2604(ECO)	Si-Di	=(NT)2602(ECO): 400V	32b		BYX 38/600R, BYX 39/600R
(NT)2606(ECO)	Si-Di	=(NT)2802(ECO): 600V	32b		BYX 38/600R, BYX 39/600R
(NT)2811(ECO)	Si-Di	Gl/S-L, 100V, 6A(Tc=100°)	32b	Ntn	BYX 38/300R, BYX 39/600R
(NT)2811..14R(ECO)	Si-Di	=(NT)2811(ECO):	32a		BYX 38/.., BYX 39/..
(NT)2812(ECO)	Si-Di	=(NT)2811(ECO): 200V	32b		BYX 38/300R, BYX 39/600R
(NT)2614(ECO)	Si-Di	=(NT)2611(ECO): 400V	32b		BYX 38/600R, BYX 39/600R
(NT)2702(ECO)	Si-Di	Gl/S-L, 20V, 3A(Tc=100°)	32b	Ntn	BYX 38/300R, BYX 39/600R
(NT)2702..10R(ECO)	Si-Di	=(NT)2702(ECO):	32a		BYX 38/.., BYX 39/..
(NT)2705(ECO)	Si-Di	=(NT)2702(ECO): 50V	32b		BYX 38/300R, BYX 39/600R
(NT)2710(ECO)	Si-Di	=(NT)2702(ECO): 100V	32b		BYX 38/300R, BYX 39/600R
(NT)2912(ECO)	Si-Di	Gl, S, 500V, 0,1A, <2,5µs	≈31a	Ntn	BA 159..159, BAY 8+F2179..91, BY 203/12, ++
(NT)2913(ECO)	Si-Di	=(NT)2912(ECO): 750V	≈31a		BA 159, BAY 90..91, BY 203/12, ++
(NT)2914(ECO)	Si-Di	=(NT)2912(ECO): 1000V	≈31a		BA 159, BAY 90..91, BY 203/12, ++
(NT)2915(ECO)	Si-Di	=(NT)2912(ECO): 1250V	≈31a		BAY 91, BY 203/12, RGP 01-12, SHG 1,5
(NT)2916(ECO)	Si-Di	=(NT)2912(ECO): 1500V	≈31a		BAY 91, BY 203/18, RGP 01-18, SHG 1,5
(NT)2917(ECO)	Si-Di	=(NT)2912(ECO): 1750V	≈31a	Ntn	BAY 91, BY 203/20, BY 584, SHG2
(NT)2918(ECO)	Si-Di	=(NT)2912(ECO): 2000V	≈31a	Ntn	BAY 91, BY 203/20, SHG2

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(NT)3004(ECO)	Ref-Di	Referenz-Modul		Ntn	—
(NT)3024(ECO)	Ref-Di	Referenz-Modul			—
(NT)3034(ECO)	Ref-Di	Referenz-Modul			—
(NT)3035(ECO)	Ref-Di	Referenz-Modul			—
(NT)3104(ECO)	Ref-Di	Referenz-Modul			—
(NT)3124(ECO)	Ref-Di	Referenz-Modul			—
(NT)3235(ECO)	Ref-Di	Referenz-Modul			—
(NT)3377(ECO)	Si-St	1V(1,5A), 1,5W	31a	Ntn	ZY1
(NT)3390(ECO)	Si-St	1V(0,1A), 0,4W	31a	Ntn	BA315, BZX62, BZX97/C0V8
(NT)3391(ECO)	Si-St	=(NT)3390(ECO): 0,25W	2c		BA315, BZX62, BZX97/C0V8
(NT)3392(ECO)	Si-St	L, 1,5V(2A), 15W	32	Ntn	—
(NT)3393(ECO)	Si-St	1,2V(0,5A), 1W	31a	Ntn	—
(NT)3396(ECO)	Si-St	sym, ±1V(±0,1A), 0,25W	2c	Ntn	—
(NT)3397(ECO)	Si-St	sym, ±0,56..0,68V(±1mA), 2,5W	≈31	Ntn	—
(NT)3398(ECO)	Si-St	sym, ±0,6..0,72V(±1mA), 2,5W	≈31	Ntn	—
(NT)3535(ECO)	Ref-Di	Referenz-Modul		Ntn	—
(NT)3701(G)(ECO)	Ref-Di	5,9..6,5V	31a	Ntn	BZV13, BZV30, BZX93, 1N828, 1N4583,++
(NT)3702(G)(ECO)	Ref-Di	5,9..6,5V	31a		BZV19, BZV29, BZX92, 1N825, 1N4582,++
(NT)3703(G)(ECO)	Ref-Di	5,9..6,5V	31a		BZV11, BZV28, BZX91, 1N823, 1N4581,++
(NT)3704(G)(ECO)	Ref-Di	5,9..6,5V	31a		BZV10, BZV27, BZX90, 1N821, 1N4580,++
(NT)3705(ECO)	Ref-Di	6,1..6,5V	31a	Ntn	—
(NT)3706(ECO)	Ref-Di	6,1..6,5V	31a		1N4894, 1N4895
(NT)3707(ECO)	Ref-Di	6,1..8,5V	31a		1N4893, 1N4894
(NT)3710(ECO)	Ref-Di	6,1..6,5V	31a	Ntn	—
(NT)3711(ECO)	Ref-Di	6,1..6,5V	31a		—
(NT)3712(ECO)	Ref-Di	6,1..6,5V	31a		BZV14, BZV31, BZX94, 1N829, 1N4584,++
(NT)3713(ECO)	Ref-Di	6,6V	31a	Ntn	—
(NT)3714(ECO)	Ref-Di	6,6V	31a		—
(NT)3722(ECO)	Ref-Di	8..8,8V	31a	Ntn	BZX51, 1N4780
(NT)3723(ECO)	Ref-Di	8..8,8V	31a		BZX52, 1N4781
(NT)3724(ECO)	Ref-Di	8..8,8V	31a		BZX53, 1N4782
(NT)3725(ECO)	Ref-Di	8..8,8V	31a		BZX54, 1N4783
(NT)3731(ECO)	Ref-Di	8..8,8V	31a	Ntn	—
(NT)3732(ECO)	Ref-Di	8..8,8V	31a		—
(NT)3733(ECO)	Ref-Di	8..8,8V	31a		—
(NT)38+A25601..04(ECO)	Z-Di	Module		Ntn	—
(NT)4120(c)(ECO)	Z-Di	10V, 15W, 10%(c=5%)	32a	Ntn	BZX98/.., BZY98/..
(NT)4121(c)(ECO)	Z-Di	=(NT)4120(c)(ECO): 11V	32a		—
(NT)4122(c)(ECO)	Z-Di	=(NT)4120(c)(ECO): 12V	32a		—
(NT)4123(c)(ECO)	Z-Di	=(NT)4120(c)(ECO): 13V	32a		—
(NT)4124(c)(ECO)	Z-Di	=(NT)4120(c)(ECO): 15V	32a		—
(NT)4125(c)(ECO)	Z-Di	=(NT)4120(c)(ECO): 16V	32a		—
(NT)4126(c)(ECO)	Z-Di	=(NT)4120(c)(ECO): 18V	32a		—
(NT)4127(c)(ECO)	Z-Di	=(NT)4120(c)(ECO): 20V	32a		—
(NT)4128(c)(ECO)	Z-Di	=(NT)4120(c)(ECO): 22V	32a		—
(NT)4129(c)(ECO)	Z-Di	=(NT)4120(c)(ECO): 24V	32a		—
(NT)4130(c)(ECO)	Z-Di	=(NT)4120(c)(ECO): 27V	32a		—
(NT)4131(c)(ECO)	Z-Di	=(NT)4120(c)(ECO): 30V	32a		—
(NT)4132(c)(ECO)	Z-Di	=(NT)4120(c)(ECO): 33V	32a		—
(NT)4133(c)(ECO)	Z-Di	=(NT)4120(c)(ECO): 36V	32a		—
(NT)4134(c)(ECO)	Z-Di	=(NT)4120(c)(ECO): 39V	32a		—
(NT)4135(c)(ECO)	Z-Di	=(NT)4120(c)(ECO): 43V	32a		—
(NT)4136(c)(ECO)	Z-Di	=(NT)4120(c)(ECO): 47V	32a		—
(NT)4137(c)(ECO)	Z-Di	=(NT)4120(c)(ECO): 51V	32a		—
(NT)4138(c)(ECO)	Z-Di	=(NT)4120(c)(ECO): 56V	32a		—
(NT)4139(c)(ECO)	Z-Di	=(NT)4120(c)(ECO): 62V	32a		—
(NT)4140(c)(ECO)	Z-Di	=(NT)4120(c)(ECO): 68V	32a		—
(NT)4141(c)(ECO)	Z-Di	=(NT)4120(c)(ECO): 75V	32a		—
(NT)4142(c)(ECO)	Z-Di	=(NT)4120(c)(ECO): 82V	32a		—
(NT)4143(c)(ECO)	Z-Di	=(NT)4120(c)(ECO): 91V	32a		—
(NT)4144(c)(ECO)	Z-Di	=(NT)4120(c)(ECO): 100V	32a		—
(NT)4145(c)(ECO)	Z-Di	=(NT)4120(c)(ECO): 110V	32a		—
(NT)4146(c)(ECO)	Z-Di	=(NT)4120(c)(ECO): 120V	32a		—
(NT)4147(c)(ECO)	Z-Di	=(NT)4120(c)(ECO): 135V	32a		—
(NT)4148(c)(ECO)	Z-Di	=(NT)4120(c)(ECO): 150V	32a		—
(NT)4149(c)(ECO)	Z-Di	=(NT)4120(c)(ECO): 165V	32a		—

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(NT)4150(c)(ECO)	Z-Di	=(NT)4120(c)(ECO): 180V	32a		—
(NT)4151(c)(ECO)	Z-Di	=(NT)4120(c)(ECO): 200V	32a		—
(NT)4220..51(ECO)	Z-Di	=(NT)4120..4151(c)(ECO):	32b	Ntn	BZY93/..R
(NT)4320..51(ECO)	Z-Di	=(NT)4120..4151(c)(ECO): 20W	32a	Ntn	BZY93/..
(NT)4420..51(ECO)	Z-Di	=(NT)4120..4151(c)(ECO): 20W	32b		BZY93/..R
(NT)4520..51(ECO)	Z-Di	=(NT)4120..4151(c)(ECO): 30W	32a	Ntn	BZY91/.., 1N3309R..3350R
(NT)4620..51(ECO)	Z-Di	=(NT)4120..4151(c)(ECO): 30W	32b	Ntn	BZY91/..R, 1N3309..3350
(NT)4720..51(ECO)	Z-Di	=(NT)4120..4151(c)(ECO): bidirektional	32	Ntn	—
(NT)4820..51(ECO)	Z-Di	=(NT)4320..4151(c)(ECO): bidirektional	32	Ntn	—
(NT)4920..51(ECO)	Z-Di	=(NT)4520..4151(c)(ECO): bidirektional	32	Ntn	—
(NT)5120..51(ECO)	Z-Di	=(NT)5320..5351(c)(ECO)	31a	Ntn	→(NT)5320..5331
(NT)5220..51(ECO)	Z-Di	=(NT)5320..C3055351(c)(ECO): bidirektional	31l		—
(NT)5320(c)(ECO)	Z-Di	10V, 1W, 10%(c=5%)	31a	Ntn	BZW22/.., BZX61.., ZPY.., 1N4740..4764+
(NT)5321(c)(ECO)	Z-Di	=(NT)5320(c)(ECO): 11V	31a		—
(NT)5322(c)(ECO)	Z-Di	=(NT)5320(c)(ECO): 12V	31a		—
(NT)5323(c)(ECO)	Z-Di	=(NT)5320(c)(ECO): 13V	31a		—
(NT)5324(c)(ECO)	Z-Di	=(NT)5320(c)(ECO): 15V	31a		—
(NT)5325(c)(ECO)	Z-Di	=(NT)5320(c)(ECO): 16V	31a		—
(NT)5326(c)(ECO)	Z-Di	=(NT)5320(c)(ECO): 18V	31a		—
(NT)5327(c)(ECO)	Z-Di	=(NT)5320(c)(ECO): 20V	31a		—
(NT)5328(c)(ECO)	Z-Di	=(NT)5320(c)(ECO): 22V	31a		—
(NT)5329(c)(ECO)	Z-Di	=(NT)5320(c)(ECO): 24V	31a		—
(NT)5330(c)(ECO)	Z-Di	=(NT)5320(c)(ECO): 27V	31a		—
(NT)5331(c)(ECO)	Z-Di	=(NT)5320(c)(ECO): 30V	31a		—
(NT)5332(c)(ECO)	Z-Di	=(NT)5320(c)(ECO): 33V	31a		—
(NT)5333(c)(ECO)	Z-Di	=(NT)5320(c)(ECO): 36V	31a		—
(NT)5334(c)(ECO)	Z-Di	=(NT)5320(c)(ECO): 39V	31a		—
(NT)5335(c)(ECO)	Z-Di	=(NT)5320(c)(ECO): 43V	31a		—
(NT)5336(c)(ECO)	Z-Di	=(NT)5320(c)(ECO): 47V	31a		—
(NT)5337(c)(ECO)	Z-Di	=(NT)5320(c)(ECO): 51V	31a		—
(NT)5336(c)(ECO)	Z-Di	=(NT)5320(c)(ECO): 56V	31a		—
(NT)5339(c)(ECO)	Z-Di	=(NT)5320(c)(ECO): 62V	31a		—
(NT)5340(c)(ECO)	Z-Di	=(NT)5320(c)(ECO): 68V	31a		—
(NT)5341(c)(ECO)	Z-Di	=(NT)5320(c)(ECO): 75V	31a		—
(NT)5342(c)(ECO)	Z-Di	=(NT)5320(c)(ECO): 82V	31a		—
(NT)5343(c)(ECO)	Z-Di	=(NT)5320(c)(ECO): 91V	31a		—
(NT)5344(c)(ECO)	Z-Di	=(NT)5320(c)(ECO): 100V	31a		—
(NT)5345(c)(ECO)	Z-Di	=(NT)5320(c)(ECO): 110V	31a		—
(NT)5346(c)(ECO)	Z-Di	=(NT)5320(c)(ECO): 120V	31a		—
(NT)5347(c)(ECO)	Z-Di	=(NT)5320(c)(ECO): 135V	31a		—
(NT)5348(c)(ECO)	Z-Di	=(NT)5320(c)(ECO): 150V	31a		—
(NT)5349(c)(ECO)	Z-Di	=(NT)5320(c)(ECO): 165V	31a		—
(NT)5350(c)(ECO)	Z-Di	=(NT)5320(c)(ECO): 180V	31a		—
(NT)5351(c)(ECO)	Z-Di	=(NT)5320(c)(ECO): 200V	31a		—
(NT)5420..51(ECO)	Z-Di	=(NT)5320..5351(c)(ECO): bidirektional	31a		—
(NT)5501(ECO)	Si-St	=NT55/C0V7	31a	Ntn	→NT55/C0V7
(NT)5502(ECO)	Si-St	=NT55/C1V4	31a		→NT55/C1V4
(NT)5503(ECO)	Si-St	=NT55/2V1	31a		→NT55/C2V1
(NT)5506(G)(ECO)	Z-Di	2,7V, 0,5W, 5%, (=NT55/C..)	31a	Ntn	BZX55/.., BZX83/.., ZPD.., 1N5223..81,++
(NT)5507(G)(ECO)	Z-Di	=(NT)5506(G)(ECO): 3V	31a		—
(NT)5508(G)(ECO)	Z-Di	=(NT)5506(G)(ECO): 3,3V	31a		—
(NT)5509(G)(ECO)	Z-Di	=(NT)5506(G)(ECO): 3,6V	31a		—
(NT)5510(G)(ECO)	Z-Di	=(NT)5508(G)(ECO): 3,9V	31a		—
(NT)5511(G)(ECO)	Z-Di	=(NT)5506(G)(ECO): 4,3V	31a		—
(NT)5512(G)(ECO)	Z-Di	=(NT)5506(G)(ECO): 4,7V	31a		—
(NT)5513(G)(ECO)	Z-Di	=(NT)5506(G)(ECO): 5,1V	31a		—
(NT)5514(G)(ECO)	Z-Di	=(NT)5506(G)(ECO): 5,6V	31a		—
(NT)5515(G)(ECO)	Z-Di	=(NT)5506(G)(ECO): 6,2V	31a		—
(NT)5516(G)(ECO)	Z-Di	=(NT)5506(G)(ECO): 6,8V	31a		—
(NT)5517(G)(ECO)	Z-Di	=(NT)5506(G)(ECO): 7,5V	31a		—
(NT)5518(G)(ECO)	Z-Di	=(NT)5506(G)(ECO): 8,2V	31a		—
(NT)5519(G)(ECO)	Z-Di	=(NT)5506(G)(ECO): 9,1V	31a		—
(NT)5520(G)(ECO)	Z-Di	=(NT)5506(G)(ECO): 10V	31a		—
(NT)5521(G)(ECO)	Z-Di	=(NT)5506(G)(ECO): 11V	31a		—
(NT)5522(G)(ECO)	Z-Di	=(NT)5506(G)(ECO): 12V	31a		—
(NT)5523(G)(ECO)	Z-Di	=(NT)5506(G)(ECO): 13V	31a		—

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(NT)5524(G)(ECO)	Z-Di	=(NT)5506(G)(ECO): 15V	31a		—
(NT)5525(G)(ECO)	Z-Di	=(NT)5506(G)(ECO): 16V	31a		—
(NT)5526(G)(ECO)	Z-Di	=(NT)5506(G)(ECO): 18V	31a		—
(NT)5527(G)(ECO)	Z-Di	=(NT)5506(G)(ECO): 20V	31a		—
(NT)5528(G)(ECO)	Z-Di	=(NT)5506(G)(ECO): 22V	31a		—
(NT)5529(G)(ECO)	Z-Di	=(NT)5508(G)(ECO): 24V	31a		—
(NT)5530(G)(ECO)	Z-Di	=(NT)5506(G)(ECO): 27V	31a		—
(NT)5531(G)(ECO)	Z-Di	=(NT)5506(G)(ECO): 30V	31a		—
(NT)5532(G)(ECO)	Z-Di	=(NT)5506(G)(ECO): 33V	31a		—
(NT)5533(G)(ECO)	Z-Di	=(NT)5506(G)(ECO): 36V	31a		—
(NT)5534(G)(ECO)	Z-Di	=(NT)5506(G)(ECO): 39V	31a		—
(NT)5535(G)(ECO)	Z-Di	=(NT)5506(G)(ECO): 43V	31a		—
(NT)5536(G)(ECO)	Z-Di	=(NT)5506(G)(ECO): 47V	31a		—
(NT)5537(G)(ECO)	Z-Di	=(NT)5506(G)(ECO): 51V	31a		—
(NT)5538(G)(ECO)	Z-Di	=(NT)5506(G)(ECO): 58V	31a		—
(NT)5539(G)(ECO)	Z-Di	=(NT)5506(G)(ECO): 62V	31a		—
(NT)5540(G)(ECO)	Z-Di	=(NT)5506(G)(ECO): 68V	31a		—
(NT)5541(G)(ECO)	Z-Di	=(NT)5506(G)(ECO): 75V	31a		—
(NT)5542(G)(ECO)	Z-Di	=(NT)5506(G)(ECO): 82V	31a		—
(NT)5543(G)(ECO)	Z-Di	=(NT)5506(G)(ECO): 91V	31a		—
(NT)5544(G)(ECO)	Z-Di	=(NT)5506(G)(ECO): 100V	31a		—
(NT)5545(G)(ECO)	Z-Di	=(NT)5508(G)(ECO): 110V	31a		—
(NT)5546(G)(ECO)	Z-Di	=(NT)5508(G)(ECO): 120V	31a		—
(NT)5547(G)(ECO)	Z-Di	=(NT)5506(G)(ECO): 130V	31a		—
(NT)5548(G)(ECO)	Z-Di	=(NT)5506(G)(ECO): 150V	31a		—
(NT)5549(G)(ECO)	Z-Di	=(NT)5506(G)(ECO): 160V	31a		—
(NT)5550(G)(ECO)	Z-Di	=(NT)5506(G)(ECO): 180V	31a		—
(NT)5551(G)(ECO)	Z-Di	=(NT)5506(G)(ECO): 200V	31a		—
(NT)7701(ECO)	Si-St	=NT77/C0V7	31a	Ntn	→NT77/0V7
(NT)7702(ECO)	Si-St	=NT77/1V4	31a	Ntn	→NT77/1V4
(NT)7706(ECO)	Z-Di	2,7V, 1,5W, 5%, (=NT77/..)	31a	Ntn	BZV47/.., BZY97/.., ZY.., 1N5913..5956
(NT)7707(ECO)	Z-Di	=(NT)7706(ECO): 3V	31a		—
(NT)7708(ECO)	Z-Di	=(NT)7706(ECO): 3,3V	31a		—
(NT)7709(ECO)	Z-Di	=(NT)7706(ECO): 3,6V	31a		—
(NT)7710(ECO)	Z-Di	=(NT)7706(ECO): 3,9V	31a		—
(NT)7711(ECO)	Z-Di	=(NT)7706(ECO): 4,3V	31a		—
(NT)7712(ECO)	Z-Di	=(NT)7708(ECO): 4,7V	31a		—
(NT)7713(ECO)	Z-Di	=(NT)7706(ECO): 5,1V	31a		—
(NT)7714(ECO)	Z-Di	=(NT)7706(ECO): 5,6V	31a		—
(NT)7715(ECO)	Z-Di	=(NT)7706(ECO): 6,2V	31a		—
(NT)7716(ECO)	Z-Di	=(NT)7706(ECO): 6,8V	31a		—
(NT)7717(ECO)	Z-Di	=(NT)7708(ECO): 7,5V	31a		—
(NT)7718(ECO)	Z-Di	=(NT)7706(ECO): 8,2V	31a		—
(NT)7719(ECO)	Z-Di	=(NT)7706(ECO): 9,1V	31a		—
(NT)7720(ECO)	Z-Di	=(NT)7706(ECO): 10V	31a		—
(NT)7721(ECO)	Z-Di	=(NT)7706(ECO): 11V	31a		—
(NT)7722(ECO)	Z-Di	=(NT)7706(ECO): 12V	31a		—
(NT)7723(ECO)	Z-Di	=(NT)7706(ECO): 13V	31a		—
(NT)7724(ECO)	Z-Di	=(NT)7706(ECO): 15V	31a		—
(NT)7725(ECO)	Z-Di	=(NT)7706(ECO): 16V	31a		—
(NT)7729(ECO)	Z-Di	=(NT)7706(ECO): 18V	31a		—
(NT)7727(ECO)	Z-Di	=(NT)7706(ECO): 20V	31a		—
(NT)7728(ECO)	Z-Di	=(NT)7706(ECO): 22V	31a		—
(NT)7729(ECO)	Z-Di	=(NT)7706(ECO): 24V	31a		—
(NT)7730(ECO)	Z-Di	=(NT)7706(ECO): 27V	31a		—
(NT)7731(ECO)	Z-Di	=(NT)7706(ECO): 30V	31a		—
(NT)7732(ECO)	Z-Di	=(NT)7706(ECO): 33V	31a		—
(NT)7733(ECO)	Z-Di	=(NT)7706(ECO): 36V	31a		—
(NT)7734(ECO)	Z-Di	=(NT)7706(ECO): 39V	31a		—
(NT)7735(ECO)	Z-Di	=(NT)7706(ECO): 43V	31a		—
(NT)7736(ECO)	Z-Di	=(NT)7706(ECO): 47V	31a		—
(NT)7737(ECO)	Z-Di	=(NT)7706(ECO): 51V	31a		—
(NT)7738(ECO)	Z-Di	=(NT)7706(ECO): 56V	31a		—
(NT)7739(ECO)	Z-Di	=(NT)7706(ECO): 62V	31a		—
(NT)7740(ECO)	Z-Di	=(NT)7706(ECO): 68V	31a		—
(NT)7741(ECO)	Z-Di	=(NT)7706(ECO): 75V	31a		—

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(NT)7742(ECO)	Z-Di	=(NT)7706(ECO): 82V	31a		—
(NT)7743(ECO)	Z-Di	=(NT)7706(ECO): 91V	31a		—
(NT)7744(ECO)	Z-Di	=(NT)7706(ECO): 100V	31a		—
(NT)7745(ECO)	Z-Di	=(NT)7706(ECO): 110V	31a		—
(NT)7746(ECO)	Z-Di	=(NT)7706(ECO): 120V	31a		—
(NT)7747(ECO)	Z-Di	=(NT)7706(ECO): 130V	31a		—
(NT)7748(ECO)	Z-Di	=(NT)7706(ECO): 150V	31a		—
(NT)7749(ECO)	Z-Di	=(NT)7706(ECO): 160V	31a		—
(NT)7750(ECO)	Z-Di	=(NT)7706(ECO): 180V	31a		—
(NT)7751(ECO)	Z-Di	=(NT)7706(ECO): 200V	31a		—
(NT)9015(ECO)	Si-Di	log. Sperrkennlinie/reverse charact.	31a	Ntn	—
(NT)9400..23(ECO)	Si-Di, Z-Di	nicht dokumentiert/no data available		old	—
(NT)9425..99(ECO)	Si-Di, Z-Di	nicht dokumentiert/no data available		old	—
(NT)9605(ECO)	Z-Di	5,8..8,8V, 0,125W	2c	Ntn	—
(NT)9606(ECO)	Z-Di	=(NT)9605: 6,4..7,2V	2c		—
(NT)9607(ECO)	Z-Di	=(NT)9605: 7,1..7,9V	2c		—
(NT)9624(ECO)	Si-Di	kV-Gl, 5kV, 0,1A	≈31a	Ntn	1N5182
(NT)9648(ECO)	Si-Di	Gl/S-L, 200V, 2A	32b	Ntn	BYX38/300R, BYX39/600R
(NT)9649(ECO)	Si-Di	kV-Gl, 1,4kV, 0,1A	≈31a	Ntn	1N1732
(NT)9650(ECO)	Si-Di	=(NT)9649(ECO): 2,8kV	≈31a		1N1733
(NT)9651(ECO)	Si-Di	=(NT)9649(ECO): 4,2kV	≈31a		1N1734
(NT)9652(ECO)	Si-Di	=(NT)9649(ECO): 5,6kV	≈31a		BYX90
(NT)9689(ECO)	Si-Di	Gl/S-L, 100V, 6A, <300ns	32a	Ntn	1N3880..3883
(NT)9690(ECO)	Si-Di	=(NT)9689(ECO):	32b		1N3880R..3883R
(NT)9700..78(ECO)	Si-Di, Z-Di	nicht dokumentiert/no data available		old	—
(NT)9779(ECO)	Si-Di	=(NT)9015(ECO): 0,25W	2c	Ntn	—
(NT)9780..99(ECO)	Si-Di, Z-Di	nicht dokumentiert/no data available		old	—
(NT)9832c(ECO)	Si-Di	Kontaktschutz/contact protect	31a	Ntn	—
(NT)9970(ECO)	Z-Di	3V, 0,25W	2c	Ntn	BZX55/.., BZX79/.., ZPD.., 1N4683..90,++
(NT)9971(ECO)	Z-Di	=(NT)9970: 3,6V	2c		—
(NT)9972(ECO)	Z-Di	=(NT)9970: 4,3V	2c		—
(NT)9973(ECO)	Z-Di	=(NT)9970: 5,1V	2c		—
(NT)9974(ECO)	Z-Di	=(NT)9970: 6,2V	2c		—
(NT)9980(ECO)	Z-Di	3V, 1W	31a	Ntn	BZW22/.., BZX81/.., ZPY.., 1N5913..20,++
(NT)9981(ECO)	Z-Di	=(NT)9980: 3,6V	31a		—
(NT)9982(ECO)	Z-Di	=(NT)9980: 4,3V	31a		—
(NT)9983(ECO)	Z-Di	=(NT)9980: 5,1V	31a		—
(NT)9984(ECO)	Z-Di	=(NT)9980: 6,2V	31a		—
(NT)9992(ECO)	Z-Di	4,3V, 15W	32a	Ntn	BZX98/.., BZY93/..
(NT)9993(ECO)	Z-Di	=(NT)9992: 5,1V	32a		—
(NT)9994(ECO)	Z-Di	=(NT)9992: 6,2V	32a		—
(S)SF	MOS-P-FET-e	=SP0610T (Typ-Code/Stempel/marking)	35		→SP0610T
(S)SG, SSG	MOS-N-FET-e	=SN7002 (Typ-Code/Stempel/marking)	35		→SN7002
(S)SH	MOS-N-FET-e	=BSS 119 (Typ-Code/Stempel/marking)	35		→BSS 119
(SI-)3050C	Hybrid-Z-IC	VC, +5V, 1,6A, 18W, Iso	17/5Pin	Sak	—
(SI-)3052P	Hybrid-Z-IC	+5V, 2A, 80W	18a	Sak	—
(SI-)3052V	Hybrid-Z-IC	lo-drop, +5V, 2A, 50W	18f	Sak	—
(SI-)3082P	Hybrid-Z-IC	+8V, 2A, 50W	18a	Sak	—
(SI-)3090C	Hybrid-Z-IC	VC, +9V, 1,5A, 18W, Iso	17/5Pin	Sak	—
(SI-)3120C	Hybrid-Z-IC	VC, +12V, 1,5A, 18W, Iso	17/5Pin	Sak	—
(SI-)3122P	Hybrid-Z-IC	+12V, 2A, 50W	18a	Sak	—
(SI-)3122V	Hybrid-Z-IC	lo-drop, +12V, 2A, 50W	18f	Sak	—
(SI-)3150C	Hybrid-Z-IC	VC, +15V, 1,5A, 18W, Iso	17/5Pin	Sak	—
(SI-)3152P	Hybrid-Z-IC	+15V, 2A, 50W	18a	Sak	—
(SI-)3152V	Hybrid-Z-IC	lo-drop, +15V, 2A, 50W	18f	Sak	—
(SI-)3240C	Hybrid-Z-IC	VC, +24V, 1,5A, 18W, Iso	17/5Pin	Sak	—
(SI-)3242P	Hybrid-Z-IC	+24V, 2A, 50W	18a	Sak	—
(SSi)B0510..0580	Si-Di	→SSi B0510..0580	27c	Sie	—
(SSi)B0810..0880	Si-Di	→SSi B0810..0880	31a	Sie	—
(SSi)C 1710	Si-Di	→SSi C 1710	27c	Sie	—
(SSi)C 1720	Si-Di	→SSi C 1720	27c	Sie	—
(SSi)C 1740	Si-Di	→SSi C 1740	27c	Sie	—
(SSi)C 1780	Si-Di	→SSi C 1780	27c	Sie	—
(SSi)C 1780	Si-Di	→SSi C 1780	27c	Sie	—
(SSi)C 2620	Si-Di	→SSi C 2620	31a	Sie	—
(SSi)C 2630	Si-Di	→SSi C 2630	31a	Sie	—

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(SSi)C4610	Si-Di	→SSiC4610		Sie	—
(SSi)C4620	Si-Di	→SSiC4620		Sie	—
-1F	Si-N	=PMST5550 (Typ-Code/Stempel/marking)	35(2mm)		→PMST5550
-1J	Si-N	=PMST2369 (Typ-Code/Stempel/marking)	35(2mm)		→PMST2369
-1K	Si-N	=PMST6428 (Typ-Code/Stempel/marking)	35(2mm)		→PMST6428
-1L	Si-N	=PMST6429 (Typ-Code/Stempel/marking)	35(2mm)		→PMST6429
-2L	Si-P	=PMST5401 (Typ-Code/Stempel/marking)	35(2mm)		→PMST5401
-G1	Si-N	=PMST5551 (Typ-Code/Stempel/marking)	35(2mm)		→PMST5551
0	C-Di	=HVU300(A) (Typ-Code/Stempel/marking)	71(1,7mm)		→HVU300(A)
01...0999		**→1...999**	**(leading zero character is ignored!)**		
010	Si-N	=SO916R (Typ-Code/Stempel/marking)	35		→SO916R
02	MOS-N-FET-e	=BST82 (Typ Code/Stempel/marking)	39		→BST62
02	Si-N	=BSX39 (Typ-Code/Stempel/marking)	35		→BSX39
026	Si-N	=SO3572R (Typ-Code/Stempel/marking)	35		→SO3572R
02BZ2.2..4.7	Z-Di	2,2..4,7V,10%,0,25W	31a	Tos	BZX46/..,BZX55..,BZX83/..,ZPD..,+
02CZ2.0..47X,Y,Z	Z-Di	SMD,2..47V,≈5%,0,2W	35p	Tos	BZX84/..,BZX68/..
02DZ2.0..47Y,Z	Z-Di	SMD,4,7..8,2V,≈3%,0,2W	71a(1,7mm)	Tos	—
03P05M	50Hz-Thy	50V,0,5A,Igt/Ih<0,2/<5mA,25µs	7b	Nec	BT149/..,TAG59-..,2N6681..85
03P1M	50Hz-Thy	=03P05M:100V	7b		BT149/..,TAG59-..,2N6681..85
03P2J	50Hz-Thy	200V,0,3A(Ta=100°C),Igt/Ih<0,2/<5mA	39b	Nec	—
03P2M	50Hz-Thy	=03P05M:200V	7b		BT149/..,TAG59-..,2N6662..85
03P3M	50Hz-Thy	=03P05M:300V	7b		BT149/..,TAG59-..,2N6663..85
03P4J	50Hz-Thy	=03P2J:400V	39b		—
03P4M	50Hz-Thy	=03P05M:400V	7b		BT149/..,TAG59-..,2N6683..85
03P4MG(C)	50Hz-Thy	400V,0,3A(Tc=30°C),Igt/Ih<0,05/<5mA	7b	Nec	BT149..,MCR606-..,TAG59-..
03P5J	50Hz-Thy	=03P2J:500V	39b		—
03P5M	50Hz-Thy	=03P05M:500V	7b		BT149/..,TAG59-..,2N6664..85
03P5MG(C)	50Hz-Thy	=03P4MG:500V	7b		BT149/..,MCR606-..,TAG59-
044	Si-N	=SO3571R (Typ-Code/Stempel/marking)	35		→SO3571R
047	Si-N	=SD3570R (Typ-Code/Stempel/marking)	35		→SD3570R
04AZ2.0..39R..Z	Z-Di	2,0..39V,≈±5%,3W	31a	Tos	BZV16/..,BZV47/..,BZX70/..,ZY..,++
04BZ5.1..24(XYZ)	Z-Di	ra,5,1..24V,±5%,0,4W		Tos	BZV39/..,1N4099..4116
04DZ2.0..5.1(XYZ)	Z-Di	2,0..5,1V,±5%,0,4W		Tos	BZX46/..,BZX55/..,BZX63/..,ZPD..,+
05AZ2.2..100R..Z	Z-Di	2,2..100V,≈±5%,0,5W	31a	Tos	BZX46/..,BZX55/..,BZX83/..,ZPD..,+
066	Si-N	=SO269R (Typ-Code/Stempel/marking)	35		→SO269R
087	Si-N	=SO502SR (Typ-Code/Stempel/marking)	35		→SO502SR
09	Si-Di	=1SS377 (Typ-Code/Stempel/marking)	35		→1SS377
09	Si-Di	=1SS378 (Typ-Code/Stempel/marking)	35(2mm)		→1SS378
091	Si-N	=SD642R (Typ-Code/Stempel/marking)	35		→SO642R
1	C-Di	=HVR187 (Typ-Code/Stempel/marking)	71(2,7mm)		→HVR187
1,5KE6.8..440(A,P)	Z-Di	TAZ,6,8..440V,1,5kW(1ms)	31a	Gie,Mot,Tho	1N5629..65,1N6267..6303
1,5KE6.6..440C,CA	Z-Di	bidirektional/back to back	31a		1N6036..72,1N6136..73
1/4M..Z10	Z-Di	±10%	31a		BZX55/..,BZX83/..,ZPD..,1N5221..61,++
1/4M..Z5	Z-Di	±5%	31a		BZX55/..,BZX83/..,ZPD..,1N5221..81,++
1/4M2.4..200(A)Z	Z-Di	2,4..200V,0,25W,±20%	31a	Mot	BZX55/..,BZX83/..,ZPD..,1N5221..81,++
10		**10...99**			
10	Si-N	=MRF9411 (Typ-Code/Stempel/marking)	44		→MRF9411
10	N-FET	=SST110 (Typ-Code/Stempel/marking)	35		→SST110
100		**100...999**			
1000		**1000...9999**			
10000		**10000...99999**			
1006	Se-Di	→AEG1006	31a	Aeg	—
100T2	Si-N	NF/S-L,120V,5A,65W	23a	Tho	BD245D,BD550,2N5759..60,2SC2706,++
101	Si-P	=FC101 (Typ-Code/Stempel/marking)	46		→FC101
102	Si-N	=FC102 (Typ-Code/Stempel/marking)	46		→FC102
103	Si-P	=FC103 (Typ-Code/Stempel/marking)	45		→FC103
104	Si-N	=FC104 (Typ-Code/Stempel/marking)	45		→FC104
104T2	Si-N	NF/S-L,60V,5A,85W	23a	Tho	BD245A,BDV91,2N4914..15,2SD895,++
105	Si-P	=FC105 (Typ-Code/Stempel/marking)	46		→FC105
1053	PIN-Di	→TDA1053	25a		—
106	Si-N	=FC106 (Typ-Code/Stempel/marking)	46		→FC106
107	Si-P	=FC107 (Typ-Code/Stempel/marking)	45		→FC107
106	Si-N	=FC108 (Typ-Code/Stempel/marking)	45		→FC108

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108T2	Si-N	=BDY57	23a	Tho	→BDY57
109	Si-P	=FC 109 (Typ-Code/Stempel/marking)	46		→FC 109
109T2	Si-N	=BDY58	23a	Tho	→BDY58
10B	Z-Di	=HZF 10BP (Typ-Code/Stempel/marking)	71 (5mm)		→HZF 10BP
10C	Z-Di	=HZF 10CP (Typ-Code/Stempel/marking)	71 (5mm)		→HZF 10CP
10D1...10	Si-Di	GI, 100...1000V, 1A	31a		→1N4001..4007
10DC1...10	Si-Di	Dual, 100...1000V, 1,8A			→2x 1N4001..4007
10SP-01..10	Si-Di	Dual, 50...1000V, 10A	≈70	Gie	—
10Y	Z-Di	=BZV 49/C10 (Typ-Code/Stempel/marking)	39		→BZV 49/C10
11	N-FET	=FC 11 (Typ-Code/Stempel/marking)	45		→FC 11
11	Si-N	=MRF9511 (Typ-Code/Stempel/marking)	44		→MRF9511
110	Si-N	=FC 110 (Typ-Code/Stempel/marking)	46		→FC 110
111	Si-P	=FC 111 (Typ-Code/Stempel/marking)	45		→FC 111
111T2	Si-N	S, 60V, 0,8W	2a	Tho	—
111T2/16	Si-N	S, 60V, 0,5W	2a		—
112	Si-N	=FC 112 (Typ-Code/Stempel/marking)	45		→FC 112
113	Si-P	=FC 113 (Typ-Code/Stempel/marking)	46		→FC 113
114	Si-N	=FC 114 (Typ-Code/Stempel/marking)	46		→FC 114
115	Si-P	=FC 115 (Typ-Code/Stempel/marking)	45		→FC 115
118	Si-N	=FC 116 (Typ-Code/Stempel/marking)	45		→FC 116
117	Si-P	=FC 117 (Typ-Code/Stempel/marking)	46		→FC 117
118	Si-N	=FC 116 (Typ-Code/Stempel/marking)	46		→FC 118
119	Si-N	=FC 119 (Typ-Code/Stempel/marking)	46		→FC 119
11B	Z-Di	=HZF 11BP (Typ-Code/Stempel/marking)	71 (5mm)		→HZF 11BP
11C	Z-Di	=HZF 11CP (Typ-Code/Stempel/marking)	71 (5mm)		→HZF 11CP
11Y	Z-Di	=BZV 49/C11 (Typ-Code/Stempel/marking)	39		→BZV 49/C11
120	Si-N	=FC 120 (Typ-Code/Stempel/marking)	46		→FC 120
121	Si-P	=FC 121 (Typ-Code/Stempel/marking)	45		→FC 121
12B	Z-Di	=HZF 12BP (Typ-Code/Stempel/marking)	71 (5mm)		→HZF 12BP
12C	Z-Di	=HZF 12CP (Typ-Code/Stempel/marking)	71 (5mm)		→HZF 12CP
12Y	Z-Di	=BZV 49/C12 (Typ-Code/Stempel/marking)	39		→BZV 49/C12
13	Si-Di	=BAS 125 (Typ-Code/Stempel/marking)	35		→BAS 125
13B	Z-Di	=HZF 13BP (Typ-Code/Stempel/marking)	71 (5mm)		→HZF 13BP
13C	Z-Di	=HZF 13CP (Typ-Code/Stempel/marking)	71 (5mm)		→HZF 13CP
13Y	Z-Di	=BZV 49/C13 (Typ-Code/Stempel/marking)	39		→BZV 49/C13
14	Si-Di	=BAS 125-04 (Typ-Code/Stempel/marking)	35		→BAS 125-04
1401	Si-N	→ED1401	7a		—
1402	Si-N	→ED1402	7a		—
142T	Si-N	≈BD 142	23a		→BD 142
14B	Si-N	=BFR 14B (Typ-Code/Stempel/marking)	52		→BFR 14B
14C	Si-N	=BFR 14C (Typ-Code/Stempel/marking)	51		→BFR 14C
15	Si-Di	=BAS 125-05 (Typ-Code/Stempel/marking)	35		→BAS 125-05
15	Si-N	=MMBT 3960 (Typ-Code/Stempel/marking)	35		→MMBT 3960
1501	Si-N	→ED 1501	7a		—
1502	Si-N	→ED 1502	7a		—
15B	Z-Di	=HZF 15BP (Typ-Code/Stempel/marking)	71 (5mm)		→HZF 15BP
15C	Z-Di	=HZF 15CP (Typ-Code/Stempel/marking)	71 (5mm)		→HZF 15CP
15IP-02..10	Si-Di	Dual, 50..1000V, 15A	≈70	Gie	—
15SP-01..10	Si-Di	Dual, 50..1000V, 15A	≈70	Gie	—
15Y	Z-Di	=BZV 49/C15 (Typ-Code/Stempel/marking)	39		→BZV 49/C15
18	Si-Di	=BAS 125-08 (Typ-Code/Stempel/marking)	35		→BAS 125-06
1601	Si-P	→ED 1601	7a		—
1602	Si-P	→ED 1602	7a		—
16029	Si-N	≈BD243C		Rca	→BD243C
16039	Si-N	≈BD243C		Rca	→BD243C
16054P	Si-Di	≈BA 159	31a	Sgs	→BA 159
16090	F-Thy	≈S 3703SF	22a	Rca	→S 3703SF
16091	F-Thy	≈S 3702S	22a	Rca	→S 3702S
16092	Si-Di	≈D2103SF	34b	Rca	→D2103SF
16093	Si-Di	≈D2103S	34b	Rca	→D2103S
16094	Si-Di	≈D2103S	34b	Rca	→D2103S
16121	F-Thy	≈S 3703SF	22a	Rca	→S 3703SF
16122	F-Thy	≈S 3702S	22a	Rca	→S 3702S
16123	Si-Di	≈D2103SF	34b	Rca	→D2103SF
16152	F-Thy	≈S 3703SF	22a	Rca	→S 3703SF
16157	F-Thy	≈S 3702S	22a	Rca	→S 3702S

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16159	Si-Di	≈D2103SF	34b	Rca	→D2103SF
16207(B)	Si-N	≈BD241A,B	17j	Rca	→BD241A,B
16298	Si-N	≈2N3055		Rca	→2N3055
16299	Si-N	≈2N3055		Rca	→2N3055
16300	Si-N	≈2N5298		Rca	→2N5296
16305	Si-N	≈BD243C	17j	Rca	→BD243C
16306	Si-P	≈BD244C	17j	Rca	→BD244C
16315	Si-N	≈BD595	17j	Rca	→BD595
16316	Si-P	≈BD598	17j	Rca	→BD598
16317	Si-N	≈BD245A	18j	Rca	→BD245A
16318	Si-P	≈BD246A	18j	Rca	→BD246A
16334	Si-N	≈BD243B		Rca	→BD243B
16335	Si-N	≈BD243B		Rca	→BD243B
16343	Si-P	≈BD244C		Rca	→BD244C
16410	F-Thy	≈S3703SF	22a	Rca	→S3703SF
16411	F-Thy	≈S3702S	22a	Rca	→S3702S
16412	Si-Di	≈D2103SF	34b	Rca	→D2103SF
16413	Si-Di	≈D2103S	34b	Rca	→D2103S
16420	F-Thy	≈S3703SF	22a	Rca	→S3703SF
16421	F-Thy	≈S3702S	22a	Rca	→S3702S
16422	Si-Di	≈D2103SF	34b	Rca	→D2103SF
16423	Si-Di	≈D2103S	34b	Rca	→D2103S
16443	F-Thy	≈TIC106M	17e	Rca	→TIC106M
16461	F-Thy	≈S3702S	22a	Rca	→S3702S
16476	F-Thy	≈S3703SF	22a	Rca	→S3703SF
16477	F-Thy	≈S3702S	22a	Rca	→S3702S
16488	50Hz-Thy	≈TAG626/600	17e	Rca	→TAG626/600
16490	F-Thy	≈S3703SF	22a	Rca	→S3703SF
16491	F-Thy	≈S3702S	22a	Rca	→S3702S
16492	Si-Di	≈D2103SF	34b	Rca	→D2103SF
16493	Si-Di	≈D2103S	34b	Rca	→D2103S
16503	Si-N	≈2N3055	23a	Rca	→2N3055
16562	Si-N	≈2N5298	17j	Rca	→2N5296
16563	Si-P	≈2N6107	17j	Rca	→2N6107
16565	Si-N	≈BD943		Rca	→BD943
16588	Si-P	≈BD944		Rca	→BD944
16606	Si-N	≈BD809	17j	Rca	→BD609
1884	Si-N	≈2N3055	23a		→2N3055
18840	F-Thy	≈S3703SF	22a	Rca	→S3703SF
16641	F-Thy	≈S3702S	22a	Rca	→S3702S
18856	Si-N	≈BU104	23a	Rca	→BU104
16688	Si-N	≈2N3055	23a	Rca	→2N3055
18890	F-Thy	≈S3703SF	22a	Rca	→S3703SF
18891	F-Thy	≈S3702S	22a	Rca	→S3702S
16810	Si-N	≈BD607	17j	Rca	→BD607
16811	Si-P	≈BD606	17j	Rca	→BD606
16837	50Hz-Thy	≈2N4101	22a	Rca	→2N4101
18888	F-Thy	≈S3703SF	22a	Rca	→S3703SF
18889	F-Thy	≈S3702S	22a	Rca	→S3702S
16924	Si-P	≈BD610	17j	Rca	→BD810
16B	Z-Di	=HZF 16BP (Typ-Code/Stempel/marking)	71 (5mm)		→HZF 16BP
16C	Z-Di	=HZF 16CP (Typ-Code/Stempel/marking)	71 (5mm)		→HZF 16CP
16Y	Z-Di	=BZV 49/C16 (Typ-Code/Stempel/marking)	39		→BZV49/C16
17	Si-Di	=BAS 125-07 (Typ-Code/Stempel/marking)	44		→BAS 125-07
1701	Si-N	→ED1701	7a		—
17018	F-Thy+Di	≈S3900S	17f	Rca	→S3900S
17019	F-Thy+Di	≈S3901S	17f	Rca	→S3901S
1702	Si-N	→ED1702	7a		—
17020	F-Thy+Di	≈S3900S	17f	Rca	→S3900S
17021	F-Thy+Di	≈S3901S	17f	Rca	→S3901S
17022	F-Thy+Di	≈S3900S	17f	Rca	→S3900S
17023	F-Thy+Di	≈S3901S	17f	Rca	→S3901S
17024	F-Thy-Di	≈S3900S	17f	Rca	→S3900S
17025	F-Thy-Di	≈S3901S	17f	Rca	→S3901S
17026	F-Thy-Di	≈S3900S	17f	Rca	→S3900S
17027	F-Thy-Di	≈S3901S	17f	Rca	→S3901S•

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17028	F-Thy-Di	≈S 3900S	17f	Rca	→S 3900S
17029	F-Thy-Di	≈S 3901S	17f	Rca	→S 3901S
17030	F-Thy-Di	≈S 3900S	17f	Rca	→S 3900S
17031	F-Thy-Di	≈S 3901S	17f	Rca	→S 3901S
17032	F-Thy-Di	≈S 3900S	17f	Rca	→S 3900S
17033	F-Thy-Di	≈S 3901S	17f	Rca	→S 3901S
17034	F-Thy-Di	≈S 3900S	17f	Rca	→S 3900S
17035	F-Thy-Di	≈S 3901S	17f	Rca	→S 3901S
17036	F-Thy-Di	≈S 3900S	17f	Rca	→S 3900S
17037	F-Thy-Di	≈S 3901S	17f	Rca	→S 3901S
17040	F-Thy-Di	≈S 3900S	17f	Rca	→S 3900S
17041	F-Thy-Di	≈S 3901S	17f	Rca	→S 3901S
17052	F-Thy-Di	≈S 3900S	17f	Rca	→S 3900S
17053	F-Thy-Di	≈S 3901S	17f	Rca	→S 3901S
17054	F-Thy-Di	≈S 3900S	17f	Rca	→S 3900S
17055	F-Thy-Di	≈S 3901S	17f	Rca	→S 3901S
17058	F-Thy-Di	≈S 3900S	17f	Rca	→S 3900S
17057	F-Thy-Di	≈S 3901S	17f	Rca	→S 3901S
17058	F-Thy-Di	≈S 3900S	17f	Rca	→S 3900S
1705F	F-Thy-Di	≈S 3900S	17f	Rca	→S 3900S
17059	F-Thy-Di	≈S 3901S	17f	Rca	→S 3901S
17062	F-Thy-Di	≈S 3900S	17f	Rca	→S 3900S
17063	F-Thy+Di	≈S 3901S	17f	Rca	→S 3901S
17085	F-Thy+Di	≈S 3901S	17f	Rca	→S 3901S
17088	F-Thy+Di	≈S 3900S	17f	Rca	→S 3900S
17074	F-Thy+Di	≈S 3900S	17f	Rca	→S 3900S
17075	F-Thy+Di	≈S 3901S	17f	Rca	→S 3901S
17076	F-Thy+Di	≈S 3900S	17f	Rca	→S 3900S
17077	F-Thy+Di	≈S 3901S	17f	Rca	→S 3901S
17078	F-Thy+Di	≈S 3900S	17f	Rca	→S 3900S
17079	F-Thy+Di	≈S 3901S	17f	Rca	→S 3901S
17080	F-Thy+Di	≈S 3900S	17f	Rca	→S 3900S
17086	F-Thy+Di	≈S 3900S	17f	Rca	→S 3900S
17087	F-Thy+Di	≈S 3901S	17f	Rca	→S 3901S
17088	F-Thy+Di	≈S 3900S	17f	Rca	→S 3900S
17089	F-Thy+Di	≈S 3901S	17f	Rca	→S 3901S
17106	Thy	≈17127	17e	Rca	→17127
17120	Thy	≈17127	22a	Rca	→17127
17122	Thy	≈17127	17e	Rca	→17127
17124	Thy	≈17127	17e	Rca	→17127
17126	Thy	≈17127	22a	Rca	→17127
17127	Thy		17e	Rca	BStC 1233S11
17132	Thy	≈17127	17e	Rca	→17127
17150	Thy	≈17127	17e	Rca	→17127
17154	Thy	≈17127	17e	Rca	→17127
17186	F-Thy+Di	→17068..89	17f	Rca	17068, 17089
17322	Si-N	=BD203	17j	Rca	→BD203
17323	Si-P	=BD204	17j	Rca	→BD204
17375	Si-N	=BD243C	17j	Rca	→BD243C
17369	Si-N	=BD317	23a	Rca	→BD317
17390	Si-P	=BD318	23a	Rca	→BD318
17391	Si-N	=BD317	23a	Rca	→BD317
174, 180, 185, 203	SAW-Filter	(surface acoustic wave)			—
17484	Si-P	=BD544		Rca	→BD544
17520	Si-P-Darl	=TIP 135	17j	Rca	→TIP 135
17521	Si-N-Darl	=TIP 130	17j	Rca	→TIP 130
17580	Si-P	=RCA8638C	23a	Rca	→RCA8836C
17581	Si-N	=RCA9116C	23a	Rca	→RCA9116C
17597	Si-N	=BD243C	17j	Rca	→BD243C
18	N-FET	=SST 108 (Typ-Code/Stempel/marking)	35		→SST 106
1801	Si-P	→ED 1801	7a		—
1802	Si-P	→ED 1802	7a		—
18022	F-Thy+Di	≈S 3900S	17f	Rca	→S 3900S
18052	F-Thy+Di	≈S 3900S	17f	Rca	→S 3900S
18053	F-Thy+Di	≈S 3901S	17f	Rca	→S 3901S
180T2	Si-N	=BDY 23	23a	Tho	→BDY23

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181	Si-N	=BFQ 181 (Typ-Code/Stempel/marking)	51		→BFQ181
18127	Thy	=17127	17e	Rca	→17127
181T2	Si-N	=BDY24	23a	Tho	→BDY24
182	Si-N	=BFQ 182 (Typ-Code/Stempel/marking)	51		→BFQ182
182T2	Si-N	=BDY25	23a	Tho	→BDY25
183T2	Si-N	=BDY26	23a	Tho	→BDY26
184T2	Si-N	=BDY27	23a	Tho	→BDY27
185T2	Si-N	=BDY28	23a	Tho	→BDY26
18B	Z-Di	=HZF 18BP (Typ-Code/Stempel/marking)	71 (5mm)		→HZF 18BP
18C	Z-Di	=HZF 18CP (Typ-Code/Stempel/marking)	71 (5mm)		→HZF 18CP
18Y	Z-Di	=BZV 49/C18 (Typ-Code/Stempel/marking)	39		→BZV 49/C18
19	N-FET	=SST 109 (Typ-Code/Stempel/marking)	35		→SST 109
193DT2	Si-N	NF/S-L, 210V, 10A, 85W, >5MHz	23a	Tho	BD245F, 2SC1586, 2SD552, 2SD583, ++
194	Si-P	=BFQ 194 (Typ-Code/Stempel/marking)	51		→BFQ194
196	Si-N	=BFQ 196 (Typ-Code/Stempel/marking)	51		→BFQ196
1A	Si-N	=BC 846AW (Typ-Code/Stempel/marking)	35(2mm)		→BC846R
1A	Si-N	=FMMT 3904(Typ-Code/Stempel/marking)	35		→FMMT3904
1A	Si-N	=KST 3904 (Typ-Code/Stempel/marking)	35		→KST 3904
1A	Si-Di	=MA 110 (Typ-Code/Stempel/marking)	71 (1,7mm)		→MA110
1A	Si-N	=MMBT 3904(Typ-Code/Stempel/marking)	35		→MMBT3904
1A	Si-N	=SXT 3904 (Typ-Code/Stempel/marking)	39		→SXT3904
1A	Si-N	=YTS 3904 (Typ-Code/Stempel/marking)	35		→YTS 3904
1A(p,s)	Si-N	=BC 846A (Typ-Code/Stempel/marking)	35		→BC846
1AG	Si-N	=2SC3339-GR (Typ-Code/Stempel/marking)	35		→2SC3339
1AG	Si-N/P	=HN1B01F-GR(Typ-Code/Stempel/marking)	48		→HN1B01F
1AG	Si-N/P	=HN1B01FU(Typ-Code/Stempel/marking)	46(2mm)		→HN1B01FU
1AL	Si-N	=2SC3339-BL(Typ-Code/Stempel/marking)	35		→2SC 3339
1AM	Si-N	=MMBT 3904(Typ-Code/Stempel/marking)	35		→MMBT3904
1AO	Si-N	=2SC 3339-O(Typ-Code/Stempel/marking)	35		→2SC 339
1AQ	Si-P	=2SB1584-Q (Typ-Code/Stempel/marking)	≈35		→2SB1584
1AQ	Si-P	=2SB779-Q(Typ-Code/Stempel/marking)	35		→2SB779
1AR	Si-P	=2SB1584-R (Typ-Code/Stempel/marking)	≈35		→2SB1584
1AR	Si-P	=2SB779-R(Typ-Code/Stempel/marking)	35		→2SB779
1AR	Si-N	=BC 846AR (Typ-Code/Stempel/marking)	35		→BC846R
1AS	Si-P	=2SB1584-S (Typ-Code/Stempel/marking)	≈35		→2SB1584
1AS	Si-P	=2SB779-S (Typ-Code/Stempel/marking)	35		→2SB779
1AS	Si-N	=BC 846AW (Typ-Code/Stempel/marking)	35(2mm)		→BC846W
1AS 027	Si-Di	=1AS029: 800V	32	Tix	BYD 14K .M, BYW55..56, 2N5062,++
1AS 029	Si-Di	contr av, 1000V, 1,5A	32	Tix	BUD14M, BYD34M, BYV96E, BYW58,++
1AY	Si-N	=2SC3339-Y (Typ-Code/Stempel/marking)	35		→2SC3339
1AY	Si-N/P	=HN1B01F-Y (Typ-Code/Stempel/marking	46		→HN1B01F
1AY	Si-N/P	=HN1B01FU-Y (Typ-Code/Stempel/marking)	46(2mm)		→HN1B01FU
1AZ6,8..330	Z-Di	Z, 6,8..330V, 10%, 1W	31a	Tos	BZW22/.., BZX61/.., ZPY.., 1N5921..58,++
1B	Si-N	=BC 846BW (Typ-Code/Stempel/marking)	35(2mm)		→BC846R
1B	Si-N	=FMMT 2222(Typ-Code/Stempel/marking)	35		→FMMT2222
1B	Si-N	=KST 2222 (Typ Code/Stempel/marking)	35		→KST2222
1B	Si-Di	=MA 111 (Typ-Code/Stempel/marking)	71 (1,7mm)		→MA111
1B	Si-N	=MMBT 2222(Typ-Code/Stempel/marking)	35		→MMBT2222
1B	Si-N	=2N2222(Typ-Code/Stempel/marking)	48		→2N2222
1B	Si-N	=YTS 2222 (Typ-Code/Stempel/marking)	35		→YTS 2222
1B(p,s)	Si-N	=BC 846B(Typ-Code/Stempel/marking)	35		→BC846
1BG	Si-N	=2SC3340-GR (Typ-Code/Stempel/marking)	35		→2SC3340
1BL	Si-N	=2SC3340-BL(Typ-Code/Stempel/marking)	35		→2SC3340
1BR	Si-N	=BC 846BR (Typ Code/Stempel/marking)	35		→BC846R
1Bs	Si-N	=BC 846BW (Typ-Code/Stempel/marking)	35(2mm)		→BC846W
1C	Si-N	=FMMT-A20 (Typ-Code/Stempel/marking)	35		→FMMT-A20
1C	Si-N	=KST 20 (Typ-Code/Stempel/marking)	35		→KST20
1C	Si-Di	=MA 112 (Typ-Code/Stempel/marking)	71 (1,7mm)		→MA112
1C	Si-N	=MMBTA 20(Typ-Code/Stempel/marking)	35		→MMBTA20
1CL	Si-N	=2SC4082-L(Typ-Code/Stempel/marking)	35(2mm)		→2SC4082
1CM	Si-N	=2SC4082-M(Typ-Code/Stempel/marking)	35(2mm)		→2SC4082
1CN	Si-N	=2SC4082-N(Typ-Code/Stempel/marking)	35(2mm)		→2SC4082
1CO	Si-N	=2SC3341-O(Typ-Code/Stempel/marking)	35		→2SC3341
1CP	Si-N	=2SC4082-P(Typ-Code/Stempel/marking)	35(2mm)		→2SC4082
1CQ	Si-N	=2SC4082-Q(Typ-Code/Stempel/marking)	35(2mm)		→2SC4082
1CY	Si-N	=2SC3341-Y(Typ-Code/Stempel/marking)	35		→2SC3341

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1D	Si-N	=BC846W (Typ-Code/Stempel/marking)	35(2mm)		→BC846W
1D	Si-N	=KST42 (Typ-Code/Stempel/marking)	35		→KST42
1D	Si-Di	=MA113 (Typ-Code/Stempel/marking)	71(1,7mm)		→MA113
1D	Si-N	=MMBTA42 (Typ-Code/Stempel/marking)	35		→MMBTA42
1D	Si-N	=SXTA42 (Typ-Code/Stempel/marking)	39		→SXTA42
1D(p)	Si-N	=BC846 (Typ-Code/Stempel/marking)	35		→BC846
1DL	Si-N	=2SC4083-L (Typ-Code/Stempel/marking)	35(2mm)		→2SC4083
1DM	Si-N	=2SC4083-M (Typ-Code/Stempel/marking)	35(2mm)		→2SC4083
1DN	Si-N	=2SC4083-N (Typ-Code/Stempel/marking)	35(2mm)		→2SC4083
1DP	Si-N	=2SC4083-P (Typ-Code/Stempel/marking)	35(2mm)		→2SC4083
1DQ	Si-N	=2SC4083-Q (Typ-Code/Stempel/marking)	35(2mm)		→2SC4083
1DR	Si-N	=2SD1328-R (Typ-Code/Stempel/marking)	35		→2SD1328
1DR	Si-N	=2SD2436-R (Typ-Code/Stempel/marking)	≈35		→2SD2436
1DS	Si-N	=2SD1328-S (Typ-Code/Stempel/marking)	35		→2SD1328
1DS	Si-N	=2SD2436-S (Typ-Code/Stempel/marking)	≈35		→2SD2436
1DT	Si-N	=2SD1328-T (Typ-Code/Stempel/marking)	35		→2SD1328
1DT	Si-N	=2SD2436-T (Typ-Code/Stempel/marking)	≈35		→2SD2436
1E	Si-N	=BC847AW (Typ-Code/Stempel/marking)	35(2mm)		→BC847W
1E	Si-N	=FMMT-A43 (Typ-Code/Stempel/marking)	35		→FMMT-A43
1E	Si-N	=KST43 (Typ-Code/Stempel/marking)	35		→KST43
1E	Si-Di	=MA114 (Typ-Code/Stempel/marking)	71(1,7mm)		→MA114
1E	Si-N	=MMBTA43 (Typ-Code/Stempel/marking)	35		→MMBTA43
1E	Si-N	=SXTA43 (Typ-Code/Stempel/marking)	39		→SXTA43
1E(p,s)	Si-N	=BC847A (Typ-Code/Stempel/marking)	35		→BC847
1EL	Si-N	=2SC4084-L (Typ-Code/Stempel/marking)	35(2mm)		→2SC4084
1EM	Si-N	=2SC4084-M (Typ-Code/Stempel/marking)	35(2mm)		→2SC4084
1EN	Si-N	=2SC4084-N (Typ-Code/Stempel/marking)	35(2mm)		→2SC4084
1EP	Si-N	=2SC4084-P (Typ-Code/Stempel/marking)	35(2mm)		→2SC4084
1EQ	Si-N	=2SC4084-Q (Typ-Code/Stempel/marking)	35(2mm)		→2SC4084
1ER	Si-N	=BC847AR (Typ-Code/Stempel/marking)	35		→BC847R
1Es	Si-N	=BC847AW (Typ-Code/Stempel/marking)	35(2mm)		→BC847W
1EZ100...200D5,10	Z-Di	100...200V, 1W, D5=5%, D10=10%	31a	Sie	BZW22/..., BZX81/..., BZX85/...,++
1F	Si-N	=2SC4543 (Typ-Code/Stempel/marking)	39		→2SC4543
1F	Si-N	=BC847BW (Typ-Code/Stempel/marking)	35(2mm)		→BC847W
1F	Si-N	=KST5550 (Typ-Code/Stempel/marking)	35		→KST5550
1F	Si-Di	=MA115 (Typ-Code/Stempel/marking)	71(1,7mm)		→MA115
1F	Si-N	=MMBT5550 (Typ-Code/Stempel/marking)	35		→MMBT5550
1F(p,s)	Si-N	=BC847B (Typ-Code/Stempel/marking)	35		→BC847
1F108	Si-Di	Schottky-Di, S, 15V, 20mA		Fui	BAT19, BAT45, 1SS108
1FP	N-FET	=2SK321-P (Typ-Code/Stempel/marking)	35		→2SK321
1FQ	N-FET	=2SK321-Q (Typ-Code/Stempel/marking)	35		→2SK321
1FR	N-FET	=2SK321-R (Typ-Code/Stempel/marking)	35		→2SK321
1FR	Si-N	=BC847BR (Typ-Code/Stempel/marking)	35		→BC847R
1FS	N-FET	=2SK321-S (Typ-Code/Stempel/marking)	35		→2SK321
1Fs	Si-N	=BC847BW (Typ-Code/Stempel/marking)	35(2mm)		→BC847W
1G	Si-N	=BC847C (Typ-Code/Stempel/marking)	35		→BC847
1G	Si-N	=BC847CW (Typ-Code/Stempel/marking)	35(2mm)		→BC847W
1G	Si-N	=FMMT-A06 (Typ-Code/Stempel/marking)	35		→FMMT-A08
1G	Si-N	=KST08 (Typ Code/Stempel/marking)	35		→KST08
1G	Si-N	=MMBTA06 (Typ-Code/Stempel/marking)	35		→MMBTA08
1GM	Si-N	=MMBTA06 (Typ-Code/Stempel/marking)	35		→MMBTA06
1GR	Si-N	=BC847CR (Typ-Code/Stempel/marking)	35		→BC847R
1Gs+A869	Si-N	=BC847CW (Typ-Code/Stempel/marking)	35(2mm)		→BC847W
1GT	Si-N	=SOA08 (Typ-Code/Stempel/marking)	35		→SOA08
1H	Si-N	=BC847W (Typ-Code/Stempel/marking)	35(2mm)		→BC847W
1H	Si-N	=FMMT-A05 (Typ-Code/Stempel/marking)	35		→FMMT-A05
1H	Si-N	=KST05 (Typ-Code/Stempel/marking)	35		→KST05
1H	Si-Di	=MA116 (Typ-Code/Stempel/marking)	71(1,7mm)		→MA118
1H	Si-N	=MMBTA05 (Typ-Code/Stempel/marking)	35		→MMBTA05
1H(p)	Si-N	=BC847 (Typ-Code/Stempel/marking)	35		→BC847
1HR	Si-N	=2SD2185-R (Typ-Code/Stempel/marking)	39		→2SD2185
1HS	Si-N	=2SD2185-S (Typ-Code/Stempel/marking)	39		→2SD2185
1HT	Si-N	=SOA05 (Typ-Code/Stempel/marking)	35		→SOA05
1I	Si-P	=2SB1440 (Typ-Code/Stempel/marking)	39		→2SB1440
1IR	Si-P	=2SB1440-R (Typ-Code/Stempel/marking)	39		→2SB1440
1IS	Si-P	=2SB1440-S (Typ-Code/Stempel/marking)	39		→2SB1440

ТИП	СТРУКТУРА	ХАРАКТЕРИСТИКИ	КОРПУС	ПРОИЗВОДИТЕЛЬ	АНАЛОГ
1J	Si-N	=BC848AW(Typ-Code/Stempel/marking)	35(2mm)		→BC848W
1J	Si-N	=FMMT2369(Typ-Code/Stempel/marking)	35		→FMMT2369
1J	Si-N	=MMBT2369(Typ-Code/Stempel/marking)	35		→MMBT2369
1J(p,s)	Si-N	=BC848A(Typ-Code/Stempel/marking)	35		→BC848
1JA	Si-N	=MMBT2369A(Typ-Code/Stempel/marking)	35		→MMBT2369A
1Jp	Si-N	=BCV61A(Typ-Code/Stempel/marking)	44		→BCV61
1JR	Si-N	=BC848AR(Typ-Code/Stempel/marking)	35		→BC848R
1Js	Si-N	=BC848AW(Typ-Code/Stempel/marking)	35(2mm)		→BC848W
1Js	Si-N	=BCV61A(Typ-Code/Stempel/marking)	44		→BCV61
1K	Si-N	=BC848B(Typ-Code/Stempel/marking)	35		→BC848
1K	Si-N	=BC848BW(Typ-Code/Stempel/marking)	35(2mm)		→BC848W
1K	Si-N	=KST6428(Typ-Code/Stempel/marking)	35		→KST6428
1K	Si-N	=MMBT6428(Typ-Code/Stempel/marking)	35		→MMBT6428
1K34(A)	Ge-Di	≈1N34	31a		→1N34
1K60	Ge-Di	≈1N60	31a		→1N60
1K90	Ge-Di	≈1N90	31a		→1N90
1KM	Si-N	=MMBT6428(Typ-Code/Stempel/marking)	35		→MMBT6428
1KP	N-FET	=2SK316-P(Typ-Code/Stempel/marking)	35		→2SK316
1Kp	Si-N	=BCV61B(Typ-Code/Stempel/marking)	44		→BCV61
1KQ	N-FET	=2SK316-Q(Typ-Code/Stempel/marking)	35		→2SK316
1KR	Si-N	=2SD2210-R(Typ-Code/Stempel/marking)	39		→2SD2210
1KR	Si-N	=BC848BR(Typ-Code/Stempel/marking)	35		→BC848R
1KS	Si-N	=2SD2210-S(Typ-Code/Stempel/marking)	39		→2SD2210
1Ks	Si-N	=BC848BW(Typ-Code/Stempel/marking)	35(2mm)		→BC848W
1Ks	Si-N	=BCV61B(Typ-Code/Stempel/marking)	44		→BCV61
1KT	Si-N	=2SD2210-T(Typ-Code/Stempel/marking)	39		→2SD2210
1L	Si-P	=2SB1537(Typ-Code/Stempel/marking)	39		→2SB1537
1L	Si-N	=BC848CW(Typ-Code/Stempel/marking)	35(2mm)		→BC848W
1L	Si-N	=MMBT6429(Typ-Code/Stempel/marking)	35		→MMBT6429
1L(p,s)	Si-N	=BC848C(Typ-Code/Stempel/marking)	35		→BC848
1LM	Si-N	=2SC4103-M(Typ-Code/Stempel/marking)	35(2mm)		→2SC4103
1LN	Si-N	=2SC4103-N(Typ-Code/Stempel/marking)	35(2mm)		→2SC4103
1LP	Si-N	=2SC4103-P(Typ-Code/Stempel/marking)	35(2mm)		→2SC4103
1Lp	Si-N	=BCV61C(Typ-Code/Stempel/marking)	44		→BCV61
1LQ	Si-N	=2SC4103-Q(Typ-Code/Stempel/marking)	35(2mm)		→2SC4103
1LR	Si-N	=BC848CR(Typ-Code/Stempel/marking)	35		→BC848R
1Ls	Si-N	=BC848CW(Typ-Code/Stempel/marking)	35(2mm)		→BC848W
1Ls	Si-N	=BCV61C(Typ-Code/Stempel/marking)	44		→BCV61
1M	Si-N	=2SD2357(Typ-Code/Stempel/marking)	39		→2SD2357
1M	Si-N	=BC848W(Typ-Code/Stempel/marking)	35(2mm)		→BC848W
1M	Si-N	=FMMT-A13(Typ-Code/Stempel/marking)	35		→FMMT-A13
1M	Si-N	=IMBT3903(Typ-Code/Stempel/marking)	35		→IMBT3903
1M	Si-N	=KST13(Typ-Code/Stempel/marking)	35		→KST13
1M	Si-N	=MMBTA13(Typ-Code/Stempel/marking)	35		→MMBTA13
1M(p)	Si-N	=BC848(Typ-Code/Stempel/marking)	35		→BC848
1M...ZS10	Z-Di	±10%	31a		BZD23/..., BZT03/..., BZX70/...
1M...ZS5	Z-Di	±5%	31a		BZD23/..., BZT03/..., BZX70/...
1M3.3...200ZS	Z-Di	3,3...200V, 2,5W, ±20%	31a	Mot	BZD23/..., BZT03/..., BZX70/...
1MN	Si-N	=2SC4128-N(Typ-Code/Stempel/marking)	35(2mm)		→2SC4128
1MP	Si-N	=2SC4128-P(Typ-Code/Stempel/marking)	35(2mm)		→2SC4128
1MP	Si-P	=2SJ84-P(Typ-Code/Stempel/marking)	35		→2SJ84
1Mp	Si-N	=BCV61(Typ-Code/Stempel/marking)	44		→BCV61
1MQ	Si-P	=2SJ34-Q(Typ-Code/Stempel/marking)	35		→2SJ34
1MR	Si-P	=2SJ34-R(Typ-Code/Stempel/marking)	35		→2SJ84

1N 1N

ТИП	СТРУКТУРА	ХАРАКТЕРИСТИКИ	КОРПУС	ПРОИЗВОДИТЕЛЬ	АНАЛОГ
1N	Si-P	=2SB1539(Typ-Code/Stempel/marking)	39		→2SB1539
1N	Si-N	=FMMT-A14(Typ-Code/Stempel/marking)	35		→FMMT-A14
1N	Si-N	=IMBT3904(Typ-Code/Stempel/marking)	35		→IMBT3904
1N	Si-N	=KST14(Typ-Code/Stempel/marking)	35		→KST14
1N	Si-N	=MMBTA14(Typ-Code/Stempel/marking)	35		→MMBTA14
1N100(A)	Ge-Di	Uni, 100V, 30...70mA	31a	USA,Tho	AA117...118, AA132...133
1N1005	Ge-Di	Gl, 380V, 0,25A			—
1N1007	Ge-Di	Gl, 380V, 0,35A			—
1N1008	Ge-Di	Gl, 380V, 0,4A			—
1N101	Ge-Di	Uni, 150V, 10mA			AA133, 1N39

ТИП	СТРУКТУРА	ХАРАКТЕРИСТИКИ	КОРПУС	ПРОИЗВОДИТЕЛЬ	АНАЛОГ
1N1013	Ge-Di	Gl, 380V, 0,25A			—
1N1016	Ge-Di	Gl, 380V, 0,4A			—
1N102	Ge-Di	Uni, 125V	31a	USA	AA133, 1N39
1N1021	Ge-Di	Gl, 380V, 0,25A			—
1N1022	Ge-Di	Gl, 380V, 0,3A			—
1N1023	Ge-Di	Gl, 380V, 0,35A			—
1N1024	Ge-Di	Gl, 380V, 0,4A			—
1N1028	Si-Di	Gl, 50V, 0,5A(Ta=100°)	≈34a	USA	BY126..127, BY133..35, 1N4001..07,++
1N1029	Si-Di	=1N1028: 100V	≈34a		BY126..127, BY133..135, 1N4002..07,++
1N103	Ge-Di	Uni, 20V	31a	USA	AA117..118, AA132..134, 1N34, 1N54,++
1N1030	Si-Di	=1N1028: 150V	≈34a		BY126..127, BY133..135, 1N4003..07,++
1N1031	Si-Di	=1N1028: 200V	≈34a		BY126..127, BY133..134, 1N4003..07,++
1N1032	Si-Di	=1N1028: 300V	≈34a		BY126..127, BY133..134, 1N4004..07,++
1N1033	Si-Di	=1N1028: 400V	≈34a		BY126..127, BY133..134, 1N4004..07,++
1N1034	Si-Di	Gl-L, 50V, 1A(Tc=100°)	≈32b	USA	BYX38/300R, BYX39/600R
1N1035	Si-Di	=1N1034: 100V	≈32b		BYX38/300R, BYX39/600R
1N1036	Si-Di	=1N1034: 150V	≈32b		BYX38/300R, BYX39/600R
1N1037	Si-Di	=1N1034: 200V	≈32b		BYX38/300R, BYX39/600R
1N1038	Si-Di	=1N1034: 300V	≈32b		BYX38/300R, BYX39/600R
1N1039	Si-Di	=1N1034: 400V	≈32b		BYX38/600R, BYX39/600R
1N104	Ge-Di	Uni, 25V	31a	USA	AA117..118, AA132..134, 1N34, 1N54,++
1N1040	Si-Di	Gl, 50V, 1A(Tc=100°)	≈32b	USA	BYX38/300R, BYX39/600R
1N1041	Si-Di	=1N1040: 100V	≈32b		BYX38/300R, BYX39/600R
1N1042	Si-Di	=1N1040: 150V	≈32b		BYX38/300R, BYX39/600R
1N1043	Si-Di	=1N1040: 200V	≈32b		BYX38/300R, BYX39/600R
1N1044	Si-Di	=1N1040: 300V	≈32b		BYX38/300R, BYX39/600R
1N1045	Si-Di	=1N1040: 400V	≈32b		BYX38/600R, BYX39/600R
1N1046	Si-Di	Gl, 50V, 1A(Tc=100°)		USA	—
1N1047	Si-Di	=1N1046: 100V			—
1N1048	Si-Di	=1N1046: 150V			—
1N1049	Si-Di	=1N1048: 200V			—
1N105	Di	UHF		Kem	—
1N1050	Si-Di	=1N1048: 300V			—
1N1051	Si-Di	=1N1048: 400V			—
1N1052	Si-Di	Gl, 50V, 1,5A(Tc=100°)	≈34a	USA	BYW52..56, BYX82..87.1N5391..97,++
1N1053	Si-Di	=1N1052: 100V	≈34a		BYW52..56, BYX82..87.1N5392..97,++
1N1054	Si-Di	=1N1052: 150V	≈34a		BYW52..56, BYX82..87.1N5393..97,++
1N1055	Si-Di	=1N1052: 200V	≈34a		BYW52..56, BYX82..87.1N5393..97,++
1N1056	Si-Di	=1N1052: 300V	≈34a		BYW53..56, BYX83..87.1N5394..97,++
1N1057	Si-Di	=1N1052: 400V	≈34a		BYW53..56, BYX83..87.1N5395..97,++
1N1058	Si-Di	Gl, 50V, 5A(Tc=100°)	32b	USA	BYX38/300R, BYX39/600R
1N1059	Si-Di	=1N1058: 100V	32b		BYX, 38/300R, BYX39/600R
1N106	Ge-Di	Uni, 300V	31a		—
1N1060	Si-Di	=1N1058: 150V	32b		BYX38/300R, BYX, 39/600R
1N1061	Si-Di	=1N1058: 200V	32b		BYX38/300R, BYX, 39/600R
1N1062	Si-Di	=1N1058: 300V	32b		BYX38/300R, BYX39/600R
1N1063	Si-Di	=1N1058: 400V	32b		BYX38/600R, BYX39/600R
1N1064	Si-Di	Gl-L, 50V, 5A(Tc=100°)	32b	USA	BYX38/300R, BYX39/600R
1N1065	Si-Di	=1N1064: 100V	32b		BYX38/300R, BYX39/600R
1N1066	Si-Di	=1N1064: 150V	32b		BYX38/300R, BYX39/600R
1N1067	Si-Di	=1N1064: 200V	32b		BYX38/300R, BYX39/600R
1N1068	Si-Di	=1N1064: 300V	32b		BYX38/300R, BYX39/600R
1N1069	Si-Di	=1N1064: 400V	32b		BYX38/600R, BYX39/600R
1N107	Ge-Di	Uni, 10V, 100mA	31a	USA	AA135..136, AA139
1N1070	Si-Di	Gl-L, 50V, 5A(Tc=100°)		USA	—
1N1071	Si-Di	=2N1070: 100V			—
1N1072	Si-Di	=2N1070: 150V			—
1N1073	Si-Di	=2N1070: 200V			—
1N1074	Si-Di	=2N1070: 300V			—
1N1075	Si-Di	=2N1070: 400V			—
1N1076	Si-Di	Gl-L, 50V, 15A(Tc=100°)		USA	—
1N1077	Si-Di	=1N1076: 100V			—
1N1078	Si-Di	=1N1076: 150V			—
1N1079	Si-Di	=1N1076: 200V			—
1N108	Ge-Di	Uni, 50V	31a	USA	AA135..136, AA139
1N1080	Si-Di	=1N1076: 300V			—

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1N1081(A)	Si-Di	Gl, 100V, 0,5..0,75A(Ta=100°)		USA	BY 126..127, BY 133..135, 1N4002..07,++
1N1082(A)	Si-Di	=1N1081(A): 200V			BY 126..127, BY 133..134, 1N4003..07,++
1N1083(A)	Si-Di	=1N1081(A): 300V			BY 126..127, BY 133..134, 1N4004..07,++
1N1084(A)	Si-Di	=1N1081(A): 400V			BY 126..127, BY 133..134, 1N4004..07,++
1N1085(A)	Si-Di	Gl, 100V, 1,5..2A(Ta=100°)		USA	BY 251..255, BYW52..56, 1N5060..82,++
1N1086(A)	Si-Di	=1N1085: 200V			BY 251..255, BYW52..56, 1N5060..62,++
1N1087(A)	Si-Di	=1N1085: 300V			BY 252..255, BYW53..56, 1N5060..62,++
1N1088(A)	Si-Di	=1N1085: 400V			BY 252..255, BYW53..56, 1N5060..62,++
1N1089(A)	Si-Di	Gl, 100V, 5A(Ta=100°)		USA	BY 214/100, MR751..760
1N109	Ge-Di	O, 15V, 50mA	31a	Kem	—
1N1090(A)	Si-Di	=1N1089: 200V			BY 214/200, MR752..760
1N1091(A)	Si-Di	=1N1089: 300V			BY 214/400, MR754..760
1N1092(A)	Si-Di	=1N1089: 400V			BY 214/400, MR754..760
1N1093	Ge-Di	S, 15V, 500ns	31a	USA,	AAY 27..28, 1N191..192, 1N3592
1N1095	Si-Di	Gl, 500V, 0,75A(Tc=50°)	34a	Rca, Tix,++	BY 126..127, BY 133..134, 1N4005..07,++
1N1096	Si-Di	=1N1095: 600V	34a		BY 126..127, BY 133..134, 1N4005..07,++
1N110	Ge-Di	UHF-M	Koax	Gie	—
1N1100	Si-Di	Gl, 100V, 0,75A(Tc=50°)	34a	USA	BY 126..127, BY 133..135, 1N4002..07,++
1N1101	Si-Di	=1N1100: 200V	34a		BY 126..127, BY 133..134, 1N4003..07,++
1N1102	Si-Di	=1N1100: 300V	34a		BY 126..127, BY 133..134, 1N4004..07,++
1N1103	Si-Di	=1N1100: 400V	34a		BY 126..127, BY 133..134, 1N4004..07,++
1N1104	Si-Di	=1N1100: 500V	34a		BY 128..127, BY 133..134, 1N4005..07,++
1N1105	Si-Di	=1N1100: 600V	34a		BY 126..127, BY 133..134, 1N4005..07,++
1N1108	Si-Di	Gl, 800V, 0,45A		USA	BA 158..159, BY 127, BY 133, BY 268,++
1N1109	Si-Di	Gl, 1200V, 0,43A		USA	BY 127, BY 133, BY 268..269,++
1N111	Ge-Di	Gl, S, 70V, 50mA	31a	USA	AA 117..118, AA 132..134, 1N34, 1N54,++
1N1110	Si-Di	Gl, 1800V, 0,4A		USA	BY 269, BY 400, DM 513, EM 516, GP 10Y
1N1111	Si-Di	Gl, 2000V, 0,38A		USA	1N1732A..1734A
1N1112	Si-Di	Gl, 2400V, 0,35A		USA	1N1733A..1734A
1N1113	Si-Di	Gl, 2800V, 0,33A		USA	1N1733A..1734A
1N1115	Si-Di	Gl, 100V, 1,5A(Tc=85°)	32a	USA, Tix	BYX 38/300, BYX 39/600
1N1115R...1120R	Si-Di	=1N1115..1120:	32b		BYX 38/600R, BYX 39/800R
1N1116	Si-Di	=1N1115: 200V	32a		BYX 38/300, BYX 39/600
1N1117	Si-Di	=1N1115: 300V	32a		BYX 38/300, BYX 39/800
1N1118	Si-Di	=1N1115: 400V	32a		BYX 38/600, BYX 39/800
1N1119	Si-Di	=1N1115: 500V	32a		BYX 38/600, BYX 39/600
1N112	Ge-Di	Gl, S, 70V, 50mA	31a	USA	AA 117..118, AA 132..134, 1N34, 1N54,++
1N1120	Si-Di	=1N1115: 600V	32a		BYX 38/600, BYX 39/600
1N1124(A)	Si-Di	Gl-L, 200V, 3..3,3A(Tc=50°)	32a	USA, Tix	BYX 38/600, BYX 39/600
1N1124R...1128R	Si-Di	=1N1124(A)..1128(A):	32b		BYX 38/600R, BYX 39/600R
1N1125(A)	Si-Di	=1N1124(A): 300V	32a		BYX 38/600, BYX 39/800
1N1126(A)	Si-Di	=1N1124(A): 400V	32a		BYX 38/600, BYX 39/600
1N1127(A)	Si-Di	=1N1124(A): 500V	32a		BYX 38/600, BYX 39/600
1N1128(A)	Si-Di	=1N1124(A): 600V	32a		BYX 38/600, BYX 39/600
1N113	Ge-Di	Gl, S, 70V, 50mA	31a	USA	AA 117..116, AA 132..134, 1N34, 1N54,++
1N1130	Si-Di	Gl-L, 1500V, 0,3A	32a	USA	—
1N1131	Si-Di	=1N1130	32b		—
1N1132(R)	Si-Di	UHF, S/X-Band-M	Koax	USA	—
1N1133	Si-Di	kV-Gl, 1,5kV, 0,075A	31a	USA	1N5181
1N1134	Si-Di	kV-Gl, 1,5kV, 0,1A	31a	USA	1N5181
1N1135	Si-Di	kV-Gl, 1,8kV, 0,085A	31a	USA	1N5181
1N1138	Si-Di	kV-Gl, 1,8kV, 0,085A	31a	USA	1N5181
1N1137	Si-Di	kV-Gl, 2,4kV, 0,05A	31a	USA	1N5181
1N1138	Si-Di	kV-Gl, 2,4kV, 0,06A	31a	USA	1N5181
1N1139	Si-Di	kV-Gl, 3,6kV, 0,085A	31a	USA	1N5181
1N114	Ge-Di	Gl, S, 70V, 50mA	31a	USA	AA 117..118, AA 132..134, 1N34, 1N54,++
1N1140	Si-Di	kV-Gl, 3,8kV, 0,085A	31a	USA	1N5181
1N1141	Si-Di	kV-Gl, 4,8kV, 0,06A	31a	USA	1N5182
1N1142	Si-Di	kV-Gl, 4,8kV, 0,05A	31a	USA	1N5182
1N1143	Si-Di	kV-Gl, 6kV, 0,05A	31a	USA	1N5183
1N1143A	Si-Di	=1N1143: 0,065mA	31a	USA	1N5183
1N1144	Si-Di	kV-Gl, 7,2kV, 0,05A	31a	USA	1N5193
1N1145	Si-Di	kV-Gl, 7,2kV, 0,06A	31a	USA	1N5183
1N1146	Si-Di	kV-Gl, 8kV, 0,045A	31a	USA	1N5184
1N1147	Si-Di	kV-Gl, 12kV, 0,045A	31a	USA	1N3052
1N1148	Si-Di	kV-Gl, 14kV, 0,05A	31a	USA	1N3053

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1N1149	Si-Di	kV-Gl, 16kV, 0,045A	31a	USA	1N3054
1N115	Ge-Di	Gl, S, 70V, 50mA	31a	USA	AA117..118, AA132..134, 1N34, 1N54,++
1N1150(A)	Si-Di	kV-Gl, 1,6kV, 0,75A		USA	—
1N1157	Si-Di	Gl-L, 50V, 20A(Tc=100°)		Edi	BYX25/600, SSi E2040
1N1158	Si-Di	=1N1157: 100V			BYX25/600, SSi E2040
1N1159	Si-Di	=1N1157: 200V			BYX25/600, SSi E2040
1N116(A)	Ge-Di	Uni, 60..C108770V, 30mA	31a	USA,Tho	AA117..118, AA132..134, 1N34, 1N54,++
1N1160	Si-Di	=1N1157: 300V			BYX25/600, SSi E2040
1N1161	Si-Di	Gl-L, 50V, 35A(Tc=100°)		Edi	BYX96/300
1N1182	Si-Di	=1N1161: 100V			BYX96/300
1N1163	Si-Di	=1N1161: 200V			BYX96/300
1N1164	Si-Di	=1N1161: 300V			BYX96/300
1N1165	Si-Di	Gl-L, 50V, 100A(Tc=100°)		Edi	DS75-02B
1N1166	Si-Di	=1N1165: 100V			DS75-02B
1N1167	Si-Di	=1N1165: 200V			DS75-02B
1N1168	Si-Di	=1N1165: 300V			DS75-04B
1N1169	Si-Di	Gl, 400V, 0,79A	31a	Inr,Sem	BY126..127, BY133..134, 1N4004..07,++
1N1169A	Si-Di	=1N1169:	34a		BY126..127, BY133..134, 1N4004..07,++
1N117(A)	Ge-Di	Uni, 60..70V, 30mA	31a	USA,Tho	AA117..18, AA132..134, 1N34, 1N54,++
1N1170	Ge-Di	Uni, 50V	31a		AA117..18, AA132..134, 1N34, 1N54,++
1N1171	Si-Di	=1N1157		Edi	→1N1157
1N1172	Si-Di	=1N1158		Edi	→1N1158
1N1173	Si-Di	=1N1159		Edi	→1N1159
1N1174	Si-Di	=1N1160		Edi	→1N1160
1N1175	Si-Di	=1N1161		Edi	→1N1161
1N1176	Si-Di	=1N1162		Edi	→1N1162
1N1177	Si-Di	=1N1163		Edi	→1N1163
1N1178	Si-Di	=1N1164		Edi	→1N1164
1N1179	Si-Di	=1N1165		Edi	→1N1165
1N118(A)	Ge-Di	Uni, 60V, 30..70mA	31a	USA,Tho	AA117..11+F11688, AA132..134, 1N34, 1N54,++
1N1160	Si-Di	=1N1166		Edi	→1N1166
1N1181	Si-Di	=1N1167		Edi	→1N1167
1N1162	Si-Di	=1N1168		Edi	→1N1168
1N1163	Si-Di	Gl-L, 50V, 35A(Tc=140°)	32a	USA,EUR	1N3765, 1N4525
1N1183A..1190A	Si-Di	=1N1183..1190: 40A(Tc=150°)			—
1N1183R..1190R	Si-Di	=1N1163..1190:	32b		1N3765R
1N1183T...1190T	Si-Di	=1N1163..1190:	73a		1N3765T
1N1183TR..1190TR	Si-Di	=1N1163..1190:	73b		1N3765TR
1N1164	Si-Di	=1N1183: 100V	32a		1N3765, 1N4525
1N1185	Si-Di	=1N1163: 150V	32a		1N3765, 1N4525
1N1166	Si-Di	=1N1183: 200V	32a		1N3765, 1N4525
1N1187	Si-Di	=1N1163: 300V	32a		1N3765, 1N4526
1N1166	Si-Di	=1N1163: 400V	32a		1N3765, 1N4526
1N1189	Si-Di	=1N1183: 500V	32a		1N3765, 1N4527
1N119	Ge-Di	Uni, S, 60V, 25mA	31a	USA	AAY28, 1N191..192, 1N276
1N1190	Si-Di	=1N1163: 600V	32a		1N3765, 1N4527
1N1191(A)	Si-Di	Gl-L, 50V, 20A(Tc=150°)	32a	USA,EUR	1N3765, 1N4525
1N1191R..1198R	Si-Di	=1N1191..1198:	32b		1N3765R
1N1192(A)	Si-Di	=1N1191: 100V	32a		1N3765, 1N4525
1N1193(A)	Si-Di	=1N1191: 150V	32a		1N3765, 1N4525
1N1194(A)	Si-Di	=1N1191: 200V	32a		1N3765, 1N4525
1N1195(A)	Si-Di	=1N1191: 300V	32a		1N3765, 1N4526
1N1196(A)	Si-Di	=1N1191: 400V	32a		1N3765, 1N4526
1N1197(A)	Si-Di	=1N1191: 500V	32a		1N3765, 1N4527
1N1196(A)	Si-Di	=1N1191: 600V	32a		1N3765, 1N4527
1N1189(A,B,C)	Si-Di	Gl-L, 50V, 12A(150°)	32a	Gen,Inr,Mot	BYW88/50, BYX75
1N1199(A,B,C)	Si-Di			Rca,Tix,++	—
1N120	Ge-Di	Uni, S, 60V, 25mA	31a	USA	AAY28, 1N191..192, 1N276
1N1200(A,B,C)	Si-Di	=1N1199: 100V	32a		BYW88/100, BYX76
1N1201(A,B,C)	Si-Di	=1N1199: 150V	32a		BYW88/200, BYX77
1N1201R...1206R	Si-Di	=1N1199..1206:	32b		BYW88/..R, BYX75R..79R
1N1202(A,B,C)	Si-Di	=1N1199: 200V	32a		BYW88/200, BYX77
1N1203(A,B,C)	Si-Di	=1N1199: 300V	32a		BYW88/300, BYX78
1N1204(A,B,C)	Si-Di	=1N1199: 400V	32a		BYW88/400, BYX78
1N1205(A,B,C)	Si-Di	=1N1199: 500V	32a		BYW88/500, BYX79
1N1208(A,B,C)	Si-Di	=1N1199: 600V	32a		BYW88/600, BYX79

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1N1217(A,B)	Si-Di	Gl, 50V, 1,6A	34a	USA	BY251..255, BYW52..56, 1N5060..62,++
1N1218(A,B)	Si-Di	=1N1217: 100V	34a		BY251..255, BYW52..56, 1N5060..82,++
1N1219(A,B)	Si-Di	=1N1217: 150V	34a		BY251..255, BYW52..56, 1N5060..62,++
1N1220(A,B)	Si-Di	=1N1217: 200V	34a		BY251..255, BYW52..56, 1N5060..82,++
1N1221(A,B)	Si-Di	=1N1217: 300V	34a		BY252..255, BYW53..56, 1N5060..62,++
1N1222(A,B)	Si-Di	=1N1217: 400V	34a		BY252..255, BYW53..56, 1N5060..62,++
1N1223(A,B)	Si-Di	=1N1217: 500V	34a		BY253..255, BYW54..56, 1N5061..62,++
1N1224(A,B)	Si-Di	=1N1217: 600V	34a		BY253..255, BYW54..56, 1N5061..82,++
1N1225(A,B)	Si-Di	=1N1217: 700V	34a		BY254..255, BYW55..56, 1N5062,++
1N1226(A,B)	Si-Di	=1N1217: 800V	34a		BY254..255, BYW55..56, 1N5062,++
1N1227(A,B)	Si-Di	=1N1217:	32a		BYX38/300, BYX39/600
1N1228(A,B)	Si-Di	=1N1218:	32a		BYX38/300, BYX39/600
1N1229(A,B)	Si-Di	=1N1219:	32a		BYX38/300, BYX39/600
1N1230(A,B)	Si-Di	=1N1220:	32a		BYX38/300, BYX39/600
1N1231(A,B)	Si-Di	=1N1221:	32a		BYX38/300, BYX39/600
1N1232(A,B)	Si-Di	=1N1222:	32a		BYX38/300, BYX39/600
1N1233(A,B)	Si-Di	=1N1223:	32a		BYX38/600, BYX39/600
1N1234(A,B)	Si-Di	=1N1224:	32a		BYX38/600, BYX39/600
1N1235(A,B)	Si-Di	=1N1225:	32a		BYX38/900, BYX39/800
1N1236(A,B)	Si-Di	=1N1226:	32a		BYX38/900, BYX39/800
1N1237	Si-Di	Dual, Gl, 1600V, 0,75A		USA	—
1N1238	Si-Di	Dual, Gl, 1600V, 0,75A		USA	—
1N1239	Si-Di	Dual, Gl, 2800V, 0,5A		USA	—
1N124(A)	Ge-Di	UHF-M	Koax	Tun	—
1N1240...1250	Si-Di	≈1N1251..1261		USA	→1N1251..1261
1N125	Ge-Di	HF/S, 30V, 30mA		Tun	—
1N1251	Si-Di	Gl, 50V, 0,5A	34a	USA	BY126..127, BY133..135, 1N4001..07,++
1N1252	Si-Di	=1N1251: 100V	34a		BY126..127, BY133..135, 1N4002..07,++
1N1253	Si-Di	=1N1251: 200V	34a		BY126..127, BY133..134, 1N4003..07,++
1N1254	Si-Di	=1N1251: 300V	34a		BY126..127, BY133..134, 1N4004..07,++
1N1255(A)	Si-Di	=1N1251: 1400V	34a		BY126..127, BY133..134, 1N4004..07,++
1N1256	Si-Di	=1N1251: 500V, 0,32A	34a		BY126..127, BY133..134, 1N4005..07,++
1N1257	Si-Di	=1N1251: 600V, 0,3A	34a		BY126..127, BY133..134, 1N4005..07,++
1N1256	Si-Di	=1N1251: 700V, 0,26A	34a		BY127, BY133, BYX95, 1N4006..07,++
1N1259	Si-Di	=1N1251: 800V, 0,27A	34a		BY127, BY133, BYX95, 1N4006..07,++
1N126(A)	Ge-Di	Uni, 60..75V, 30mA	31a	USA, Tho	AA117..118, AA132..134, 1N34, 1N54,++
1N1260	Si-Di	=1N1251: 800V, 0,25A	34a		BY127, BY133, BYX95, 1N4007,++
1N1261	Si-Di	=1N1251: 1000V, 0,24A	34a		BY127, BY133, BYX95, 1N4007,++
1N1262	Si-Di	kv-Gl, 4,5kV, 0,25A		USA	—
1N1263	Si-Di	Gl, 50V, 150A			—
1N1283A...1266A	Si-Di	=1N1263..1266: 200A			—
1N1264	Si-Di	=1N1263: 100V			—
1N1265	Si-Di	=1N1263: 200V			—
1N1268	Si-Di	=1N1263: 300V			—
1N1267	Si-Di	Gl-L, 50V, 150A			—
1NA11921267A...1270A	Si-Di	=1N1267..1270: 200A			—
1N1268	Si-Di	=1N1267: 100V			—
1N1269	Si-Di	=1N1267: 200V			—
1N127(A)	Ge-Di	Uni, 100..125V, 30mA	31a	USA, Tho	AA117..118, AA132..133
1N1270	Si-Di	=1N1267: 300V			—
1N1271...1277	Si-Di	≈1N1281..1287			—
1N128(A)	Ge-Di	Uni, 40V, 30mA	31a	USA, Tho	AA117..118, AA132..134, 1N34, 1N54,++
1N1281	Si-Di	Gl-L, 50V, 160A	73a	USA	—
1N1282	Si-Di	=1N1261: 100V	73a		—
1N1283	Si-Di	=1N1261: 150V	73a		—
1N1264	Si-Di	=1N1281: 200V	73a		—
1N1285	Si-Di	=1N1281: 300V	73a		—
1N1286	Si-Di	=1N1281: 400V	73a		—
1N1287	Si-Di	=1N1281: 500V	73a		—
1N1291...1297	Si-Di	≈1N1281..1287	73a		—
1N1301	Si-Di	Gl-L, 50V, 37A(Tc=120°)	32a	USA	1N3765, 1N4525
1N1302	Si-Di	=1N1301: 100V	32a		1N3765, 1N4525
1N1304	Si-Di	=1N1301: 200V	32a		1N3785, 1N4525
1N1306	Si-Di	=1N1301: 300V	32a		1N3785, 1N4526
1N1313	Z-Di	8,75V, 10%, 0,15W	2c	USA	BZX55.., BZX79/.., ZPD.., 1N5238..74,++
1N1313A...1327A	Z-Di	=1N1313...1327: 5%	2c		—

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1N1314	Z-Di	=1N1313: 10,5V	2c		—
1N1315	Z-Di	=1N1313: 12,75V	2c		—
1N1316	Z-Di	=1N1313: 15,75V	2c		—
1N1317	Z-Di	=1N1313: 19V	2c		—
1N1316	Z-Di	=1N1313: 23,5V	2c		—
1N1319	Z-Di	=1N1313: 26,5V	2c		—
1N132	Ge-Di	UHF-M	31a	Kem	—
1N1320	Z-Di	=1N1313: 34,5V	2c		—
1N1321	Z-Di	=1N1313: 41V	2c		—
1N1322	Z-Di	=1N1313: 46,5V	2c		—
1N1323	Z-Di	=1N1313: 58V	2c		—
1N1324	Z-Di	=1N1313: 71V	2c		—
1N1325	Z-Di	=1N1313: 67,5V	2c		—
1N1326	Z-Di	=1N1313: 105V	2c		—
1N1327	Z-Di	=1N1313: 127,5V	2c		—
1N1329	Si-Di	Gl, 1500V, 0,1A		Tix	BAY91, BY203/16, BY584, RGP01/16, ++
1N133	Ge-Di	HF-Dem, 5V	31a	USA	—
1N1330	Si-Di	Gl-L, 50V, 240A(Tc=125°)	≈73a	Sem,Ssi	—
1N1331	Si-Di	=1N1330: 100V	≈73a		—
1N1332	Si-Di	=1N1330: 150V	≈73a		—
1N1333	Si-Di	=1N1330: 200V	≈73a		—
1N1334	Si-Di	=1N1330: 300V	≈73a		—
1N1335	Si-Di	=1N1330: 400V	≈73a		—
1N1336	Si-Di	=1N1330: 500V	≈73a		—
1N134	Si-Di	UHF-Dem, 5V		Kem	—
1N1341(A,B,C)	Si-Di	Gl-L, 50V, 6A(Tc=150°)	32a	Gen,Mot,Tho	BYX38/300, BYX39/600
1N1341(A,B,C)	Si-Di			++	—
1N1341R...1346R	Si-Di	=1N1341..1346	32b		BYX38/600R, BYX39/600R
1N1342(A,B,C)	Si-Di	=1N1341: 100V	32a		BYX38/300, BYX39/600
1N1343(A,B,C)	Si-Di	=1N1341: 150V	32a		BYX38/300, BYX39/600
1N1344(A,B,C)	Si-Di	=1N1341: 200V	32a		BYX38/300, BYX39/600
1N1345(A,B,C)	Si-Di	=1N1341: 300V	32a		BYX38/300, BYX39/600
1N1346(A,B,C)	Si-Di	=1N1341: 400V	32a		BYX38/600, BYX39/600
1N1347(A,B,C)	Si-Di	=1N1341: 500V	32a		BYX38/600, BYX39/600
1N1348(A,B,C)	Si-Di	=1N1341: 600V	32a		BYX38/600, BYX39/600
1N135	Ge-Di	Uni, 75V	31a	USA,Tho	AA117..118, AA132..133, 1N34, 1N54
1N1351	Z-Di	10V, 10%, 10W(Tc=55°)	32b	USA,Sie	BZX98/.., BZY93/.., 1N2974..3005
1N1351A...1375A	Z-Di	=1N1351..1375: 5%	32b		—
1N1351B...1375B	Z-Di	=1N1351..1375: 20%	32b		—
1N1351C...1375C	Z-Di	=1N1351..1375: bidirektional	32b		—
1N1351CA...1+A1607375CAZ-Di		=1N1351..1375: bidirektional, 5%	32b		—
1N1351R...1375R	Z-Di	=1N1351..1375:	32a		—
1N1352	Z-Di	=1N1351: 11V	32b		—
1N1353	Z-Di	=1N1351: 12V	32b		—
1N1354	Z-Di	=1N1351: 13V	32b		—
1N1355	Z-Di	=1N1351: 15V	32b		—
1N1356	Z-Di	=1N1351: 16V	32b		—
1N1357	Z-Di	=1N1351: 16V	32b		—
1N1356	Z-Di	=1N1351: 20V	32b		—
1N1359	Z-Di	=1N1351: 22V	32b		—
1N138	Si-Di	UHF-M		Syl	—
1N1360	Z-Di	=1N1351: 24V	32b		—
1N1361	Z-Di	=1N1351: 27V	32b		—
1N1362	Z-Di	=1N1351: 30V	32b		—
1N1363	Z-Di	=1N1351: 33V	32b		—
1N1364	Z-Di	=1N1351: 36V	32b		—
1N1385	Z-Di	=1N1351: 39V	32b		—
1N1386	Z-Di	=1N1351: 43V	32b		—
1N1387	Z-Di	=1N1351: 47V	32b		—
1N1366	Z-Di	=1N1351: 51V	32b		—
1N1369	Z-Di	=1N1351: 56V	32b		—
1N137	Si-N+R	=RT1N137L (Typ-Code/Stempel/marking)	7(9mm)		→RT1N137L
1N137(A,B)	Si-Di	Uni, 32..36V, 30..75mA	2c	USA	BA127, BA147/50, 1N4148, 1N5194..96, ++
1N1370	Z-Di	=1N1351: 62V	32b		—
1N1371	Z-Di	=1N1351: 68V	32b		—
1N1372	Z-Di	=1N1351: 75V	32b		—

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1N1373	Z-Di	=1N1351:82V	32b		—
1N1374	Z-Di	=1N1351:91V	32b		—
1N1375	Z-Di	=1N1351:100V	32b		—
1N1376	Si-Di	Gl-L, 50V, 240A(Tc=125°C)	≈73a	Sem,Ssi	—
1N1377	Si-Di	=1N1376:100V	≈73a		—
1N1376	Si-Di	=1N1376:150V	≈73a		—
1N1379	Si-Di	=1N1376:200V	≈73a		—
1N138(A,B)	Si-Di	Uni, 16..18V, 9..50mA	2c	USA	BA127, BA147/25, 1N4148, 1N5194..96,++
1N1380	Si-Di	=1N1376:300V	≈73a		—
1N1381	Si-Di	=1N1376:400V	≈73a		—
1N1382	Si-Di	=1N1376:500V	≈73a		—
1N139	Ge-Di	Uni, 46V, 70mA	31a	USA	AA117..118, AA132..134, 1N34, 1N54,++
1N1396	Si-Di	Gl-L, 50V, 70A(Tc=150°)	73a	Sem,Ssi	1N3288
1N1397	Si-Di	=2N1396:100V	73a		1N3288
1N1396	Si-Di	=2N1396:150V	73a		1N3289
1N1399	Si-Di	=2N1396:200V	73a		1N3289
1N140	Ge-Di	Uni, 80V, 85mA	31a	USA	AA117..118, AA132..133, 1N34, 1N54
1N1400	Si-Di	=2N1396:300V	73a		1N3290
1N1401	Si-Di	=2N1396:400V	73a		1N3291
1N1402	Si-Di	=2N1396:500V	73a		1N3292
1N1403	Si-Di	=2N1396:600V	73a		1N3293
1N1406	Si-Di	Gl, 600V, 0,125A	34a	Inr,Sem,Ssi	BY203/12, RGP01/10, SHG1
1N1407	Si-Di	=1N1406:800V	34a		BY203/12, RGP01/10, SHG1
1N1408	Si-Di	=1N1406:1000V	34a		BY203/12, RGP01/10, SHG1
1N1409	Si-Di	=1N1406:1200V	34a		BY203/12, RGP01/12, SHG1,5
1N141	Ge-Di	Uni, HF-Dem, 80V, 70mA	31a	USA	AA113, 1N34, 1N54
1N1410	Si-Di	=1N1406:1500V	31a		BY203/16, RGP01/16, SHG1,5
1N1411	Si-Di	=1N1406:1800V	31a		BY203/20, SHG2
1N1412	Si-Di	=1N1406:2000V	31a		BY203/20, SHG2
1N1413	Si-Di	=1N1406:2400V	31a		SHG2,5
1N1414	Si-Di	GL, 400V, 10A		Whs	BYX42/600, BYX98/600, SSi D0440
1N1415	Si-Di	GL, 400V, 1A	≈34a	USA	BY126..127, BY133..134, 1N4004..07,++
1N1416	Z-Di	8,2V, 5%, 10W	32	Sem,Ssi	BZX98/.., BZY93/.., 1N2972..3011
1N1417	Z-Di	=1N1416:12V	32		—
1N1418	Z-Di	=1N1416:15V	32		—
1N1419	Z-Di	=1N1416:18V	32		—
1N142	Ge-Di	Uni, 115V, 80mA	31a	USA	AA117..118, AA132..133
1N1420	Z-Di	=1N1416:22V	32		—
1N1421	Z-Di	=1N1416:27V	32		—
1N1422	Z-Di	=1N1416:88V	32		—
1N1423	Z-Di	=1N1416:100V	32		—
1N1424	Z-Di	=1N1416:150V	32		—
1N1425	Z-Di	8,2V, 5%, 1W	≈34a	Sem,Ssi	BZW22/.., BZX61/.., ZPY.., 1N5923..53,++
1N1426	Z-Di	=1N1425:12V	≈34a		—
1N1427	Z-Di	=1N1425:15V	≈34a		—
1N1428	Z-Di	=1N1425:18V	≈34a		—
1N1429	Z-Di	=1N1425:22V	≈34a		—
1N143	Ge-Di	Uni, 115V, 85mA	31a	USA	AA117..118, AA132..133
1N1430	Z-Di	=1N1425:27V	≈34a		—
1N1431	Z-Di	=1N1425:68V	≈34a		—
1N1432	Z-Di	=1N1425:100V	≈34a		—
1N1433	Z-Di	=1N1425:150V	≈34a		—
1N1434	Si-Di	Gl-L, 50V, 30A	32a	USA	1N3765, 1N4525
1N1435	Si-Di	=1N1434:100V	32a		1N3765, 1N4525
1N1436	Si-Di	=1N1434:200V	32a		1N3765, 1N4525
1N1437	Si-Di	=1N1434:400V	32a		1N3765, 1N4526
1N1436	Si-Di	=1N1434:600V	32a		1N3785, 1N4526
1N1439	Si-Di	Gl, 100V, 0,75A	31a	USA	BY126..127, BY133..135, 1N4002..07,++
1N144	Ge-Di	Uni, 35V, 150mA	31a	USA	AA136, 1N270
1N1440	Si-Di	=1N1439:200V	31a		BY126..127, BY133..134, 1N4003..07,++
1N1441	Si-Di	=1N1439:300V	31a		BY126..127, BY133..134, 1N4004..07,++
1N1442	Si-Di	=1N1439:400V	31a		BY126..127, BY133..134, 1N4004..07,++
1N1443(A,B)	Si-Di	GL, 1000V, 0,95..1,6A	34a	USA	BY255, BYW56, GP15M, 1N5399,++
1N1444(A,B)	Si-Di	=1N1443(A,B):	≈32a		—
1N1445	Si-Di	Gl, 300V, 0,2A			BA157..159, BAY21, BAY88..90,++
1N1446	Si-Di	GL, 100V, 1,5A(Tc=120°)		Scn,Sem	—

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1N1447	Si-Di	=1N1446: 200V			—
1N1448	Si-Di	=1N1446: 300V			—
1N1449	Si-Di	=1N1446: 400V			—
1N145	Ge-Di	Uni, 40V, 0,7A(ss)	31a	USA	AA117..118, AA132..134, 1N34, 1N54,++
1N1450	Si-Di	GL, 100V, 1,5A(Tc=100°)		Scn,Sem	—
1N1451	Si-Di	=1N1450: 200V			—
1N1452	Si-Di	=1N1450: 300V			—
1N1453	Si-Di	=1N1450: 400V			—
1N1454	Si-Di	GI-L, 100V, 25A		Ssi	—
1N1455	Si-Di	=1N1454: 200V			—
1N1456	Si-Di	=1N1454: 300V			—
1N1457	Si-Di	=1N1454: 400V			—
1N1458	Si-Di	GI-L, 100V, 35A		Ssi	—
1N1459	Si-Di	=1N1458: 200V			—
1N1460	Si-Di	=1N1458: 300V			—
1N1461	Si-Di	=1N1458: 400V			—
1N1462	Si-Di	GI-L, 100V, 50A		Ssi	—
1N1463	Si-Di	=1N1462: 200V			—
1N1464	Si-Di	=1N1462: 300V			—
1N1465	Si-Di	=1N1462: 400V			—
1N1466	Si-Di	GI-L, 100V, 75A		Ssi	—
1N1467	Si-Di	=1N1466: 200V			—
1N1468	Si-Di	=1N1466: 300V			—
1N1469	Si-Di	=1N1466: 400V			—
1N147(A)	Ge-Di	UHF-M, 900MHz	31a	Phc,Tho	—
1N1470	Si-Di	GI-L, 100V, 100A		Ssi	—
1N1471	Si-Di	=1N1470: 200V			—
1N1472	Si-Di	=1N1470: 300V			—
1N1473	Si-Di	=1N1470: 400V			—
1N1474	Si-Di	GI-L, 100V, 150A		Ssi	—
1N1475	Si-Di	=1N1474: 200V			—
1N1476	Si-Di	=1N1474: 300V			—
1N1477	Si-Di	=1N1474: 400V			—
1N1478	Si-Di	GI-L, 100V, 200A		Ssi	—
1N1479	Si-Di	=1N1478: 200V			—
1N148	Ge-Di	Dem, 15V		Cbs	—
1N1480	Si-Di	=1N1478: 300V			—
1N1481	Si-Di	=1N1478: 400V			—
1N1482	Z-Di	4,7V, 5%, 10W	32	USA	BZX98/.., BZY93/.., 1N3995..3998
1N1483	Z-Di	6,2V, 5%, 10W	32		—
1N1484	Z-Di	4,7V, 5%, 1W	≈34a	USA	BZW22/.., BZX61/.., ZPY.., 1N5917..20,++
1N1485	Z-Di	6,2V, 5%, 1W	≈34a		—
1N1486	Si-Di	GI, 500V, 0,75A	34a	USA	BY126..127, BY133..134, 1N4005..07,++
1N1487	Si-Di	GI, 100V, 0,75A	34a	USA,Tix	BY126..127, BY133..135, 1N4002..07,++
1N1488	Si-Di	=1N1487: 200V	34a		BY126..127, BY133..134, 1N4003..07,++
1N1489	Si-Di	=1N1487: 300V	34a		BY126..127, BY133..134, 1N4004..07,++
1N149	Si-Di	UHF, X-Band-M	Koax	USA	—
1N1490	Si-Di	=1N1487: 400V	34a		BY126..127, BY133..134, 1N4004..07,++
1N1491	Si-Di	=1N1487: 500V	34a		BY126..127, BY133..134, 1N4005..07,++
1N1492	Si-Di	=1N1487: 600V	34a		BY126..127, BY133..134, 1N4005..07,++
1N150	Si-Di	UHF, C-Band-M	Koax	USA	—
1N1507	Z-Di	3,9V, 10%, 0,75W	34a	USA,Mot	BZV85/.., BZW22/.., ZPY.., 1N4730..50,++
1N1507A..1517A	Z-Di	=1N1507..1517: 5%	34a		—
1N1508	Z-Di	=1N1507: 4,7V	34a		—
1N1509	Z-Di	=1N1507: 5,6V	34a		—
1N151	Ge-Di	GI, 100V, 1,2A	(Stack)	Gen	—
1N1510	Z-Di	=1N1507: 6,8V	34a		—
1N1511	Z-Di	=1N1507: 8,2V	34a		—
1N1512	Z-Di	=1N1507: 10V	34a		—
1N1513	Z-Di	=1N1507: 12V	34a		—
1N1514	Z-Di	=1N1507: 15V	34a		—
1N1515	Z-Di	=1N1507: 18V	34a		—
1N1516	Z-Di	=1N1507: 22V	34a		—
1N1517	Z-Di	=1N1507: 27V	34a		—
1N1518	Z-Di	3,9V, 10%, 1W	34a	USA,Mot	BZW22/.., BZX61/.., ZPY.., 1N5915..35,++
1N1518...1528A	Z-Di	=1N1518..1528: 5%	34a		—

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1N1519	Z-Di	=1N1518: 4,7V	34a		—
1N152	Ge-Di	Gl, 200V, 1A	(Stack)	Gen	—
1N1520	Z-Di	=1N1518: 5,6V	34a		—
1N1521	Z-Di	=1N1518: 6,8V	34a		—
1N1522	Z-Di	=1N1518: 8,2V	34a		—
1N1523	Z-Di	=1N1518: 10V	34a		—
1N1524	Z-Di	=1N1518: 12V	34a		—
1N1525	Z-Di	=1N1518: 15V	34a		—
1N1526	Z-Di	=1N1518: 18V	34a		—
1N1527	Z-Di	=1N1518: 22V	34a		—
1N1528	Z-Di	=1N1518: 27V	34a		—
1N153	Ge-Di	Gl, 300V, 0,75A	(Stack)	Gen	—
1N1530	Ref-Di	8,4V, ±0,002%/°C, 5%, 0,25W		Inr, Mot, ++	BZX53, 1N3156, 1N4777, 1N4782
1N1530A	Ref-Di	=1N1530: 0,001%/°C			BZX54, 1N3157, 1N4778, 1N4783
1N1537	Si-Di	Gl-L, 50V, 1,6A(Tc=140°)	32a	USA	BYX38/300, BYX39/600
1N1538	Si-Di	=1N1537: 100V	32a		BYX38/300, BYX39/600
1N1539	Si-Di	=1N1537: 150V	32a		BYX38/300, BYX39/600
1N1540	Si-Di	=1N1537: 200V	32a		BYX38/300, BYX39/600
1N1541	Si-Di	=1N1537: 300V	32a		BYX38/300, BYX39/600
1N1542	Si-Di	=1N1537: 400V	32a		BYX38/600, BYX39/600
1N1543	Si-Di	=1N1537: 500V	32a		BYX38/600, BYX39/600
1N1544	Si-Di	=1N1537: 600V	32a		BYX38/600, BYX39/600
1N155(A)	Si-Di	UHF-Dem, 9GHz	Koax	Syl	—
1N1551	Si-Di	Gl-L, 100V, 1A(Tc=100°)	32a	USA	BYX38/300, BYX39/600
1N1552	Si-Di	=1N1551: 200V	32a		BYX38/300, BYX39/600
1N1553	Si-Di	=1N1551: 300V	32a		BYX38/300, BYX39/600
1N1554	Si-Di	=1N1551: 400V	32a		BYX38/600, BYX39/600
1N1555	Si-Di	=1N1551: 500V	32a		BYX38/600, BYX39/600
1N1556	Si-Di	Gl, 100V, 0,75A(Tc=100°)	34a	USA	BY126..127, BY133..135, 1N4002..07, ++
1N1557	Si-Di	=1N1556: 200V	34a		BY126..127, BY133..134, 1N4003..07, ++
1N1558	Si-Di	=1N1556: 300V	34a		BY126..127, BY133..134, 1N4004..07, ++
1N1559	Si-Di	=1N1556: 400V	34a		BY126..127, BY133..134, 1N4004..07, ++
1N156	Si-Di	UHF, X-Band-M	Koax	Syl	—
1N1560	Si-Di	=1N1556: 500V	34a		BY126..127, BY133..134, 1N4005..07, ++
1N1561	Ge-Di	25V			—
1N1562	Ge-Di	25V			—
1N1563(A)	Si-Di	Gl, 100V, 1,5A	≈2c	Sem, Ssi	BY251..255, BYW52..56, 1N5392..99, ++
1N1564(A)	Si-Di	=1N1563: 200V	≈2c		BY251..255, BYW52..56, 1N5393..99, ++
1N1565(A)	Si-Di	=1N1563: 300V	≈2c		BY252..255, BYW53..56, 1N5394..99, ++
1N1566(A)	Si-Di	=1N1563: 400V	≈2c		BY252..255, BYW53..56, 1N5395..99, ++
1N1587(A)	Si-Di	=1N1563: 500V	≈2c		BY253..255, BYW54..56, 1N5398..99, ++
1N1568(A)	Si-Di	=1N1563: 600V	≈2c		BY253..255, BYW54..56, 1N5398..99, ++
1N1569	Si-Di	Gl, 100V, 1A		Mot	BY126..127, BY133..135, 1N4002..07, ++
1N157	Si-Di	≈1N21			—
1N1570	Si-Di	=1N1569: 200V			BY126..127, BY133..134, 1N4003..07, ++
1N1571	Si-Di	=1N1569: 300V			BY126..127, BY133..134, 1N4004..07, ++
1N1572	Si-Di	=1N1569: 400V			BY126..127, BY133..134, 1N4004..07, ++
1N1573	Si-Di	=1N1569: 500V			BY126..127, BY133..134, 1N4005..07, ++
1N1574	Si-Di	=1N1569: 600V			BY126..127, BY133..134, 1N4005..07, ++
1N1575	Si-Di	Gl-L, 100V, 3,5A(Tc=25°)	21	Gie, Mot, Ssi	BYX38/300, BYX39/600
1N1576	Si-Di	=1N1575: 200V	21		BYX38/300, BYX39/800
1N1577	Si-Di	=1N1575: 300V	21		BYX38/300, BYX39/600
1N1578	Si-Di	=1N1575: 400V	21		BYX38/600, BYX39/600
1N1579	Si-Di	=1N1575: 500V	21		BYX38/600, BYX39/600
1N156	Ge-Di	Gl, 300V, 0,5A	(Stack)	Gen	—
1N1560	Si-Di	=1N1575: 600V	21		BYX38/600, BYX39/600
1N1581	Si-Di	Gl-L, 50V, 10A(Tc=50°)	32a	USA, Tho	BYX88/50, BYX42/300, BYX98/300, ++
1N1581R...1587R	Si-Di	≈1N1561..1587:	32b		BYX88/..R, BYX42/..R, BYX98/..R, ++
1N1562	Si-Di	=1N1561: 100V	32a		BYX88/100, BYX42/300, BYX98/300, ++
1N1563	Si-Di	=1N1561: 200V	32a		BYX88/200, BYX42/300, BYX98/300, ++
1N1564	Si-Di	=1N1581: 300V	32a		BYX88/300, BYX42/300, BYX98/300, ++
1N1585	Si-Di	=1N1561: 400V	32a		BYX88/400, BYX42/600, BYX98/600, ++
1N1586	Si-Di	=1N1561: 500V	32a		BYX88/500, BYX42/600, BYX98/600, ++
1N1587	Si-Di	=1N1581: 600V	32a		BYX88/600, BYX42/600, BYX98/600, ++
1N1588	Z-Di	3,9V, 10%, 3,5W	32a	USA, Mot	BZX98/.., BZY93/.., 1N2970..2988
1N1588A...1598A	Z-Di	=1N1588..1598: 5%	32a		—

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1N1589	Z-Di	=1N1588: 4,7V	32a		—
1N1590	Z-Di	=1N1588: 5,6V	32a		—
1N1591	Z-Di	=1N1588: 6,8V	32a		—
1N1592	Z-Di	=1N1588: 8,2V	32a		—
1N1593	Z-Di	=1N1588: 10V	32a		—
1N1594	Z-Di	=1N1588: 12V	32a		—
1N1595	Z-Di	=1N1588: 15V	32a		—
1N1596	Z-Di	=1N1588: 18V	32a		—
1N1597	Z-Di	=1N1588: 22V	32a		—
1N1596	Z-Di	=1N1588: 27V	32a		—
1N1599	Z-Di	3,9V, 10%, 10W	32a	USA,Mot	BZX98/.., BZY93/.., 1N2970..2988
1N1599A...1609A	Z-Di	=1N1599..1609: 5%	32a		—
1N160	Si-Di	UHF,C-Band-M	Koax	USA	—
1N1600	Z-Di	=1N1599: 4,7V	32a		—
1N1601	Z-Di	=1N1599: 5,6V	32a		—
1N1602	Z-Di	=1N1599: 6,8V	32a		—
1N1603	Z-Di	=1N1599: 6,2V	32a		—
1N1604	Z-Di	=1 N1599: 10V	32a		—
1N1605	Z-Di	=1 N1599: 12V	32a		—
1N1606	Z-Di	=1 N1599: 15V	32a		—
1N1607	Z-Di	=1 N1589: 18V	32a		—
1N1606	Z-Di	=1 N1599: 22V	32a		—
1N1609	Z-Di	=1 N1599: 27V	32a		—
1N1610	Si-Di	UHF, S/X-Band-Dem	Koax	USA	—
1N1611(A,B)	Si-Di	UHF,C/X-Band-Dem	Koax	USA	—
1N1612(A)	Si-Di	Gl-L, 50V, 15A(Tc=50°)	32a	Gen,Idc,Rca	BYX25/600, BYX99/300
1N1612(A)	Si-Di			Tix,++	—
1N1612R..1616R	Si-Di	=1N1612..1616:	32b		BYX25/..R, BYX99/..R, SSi E2040
1N1613(A)	Si-Di	=1N1612: 100V	32a		BYX25/600, BYX99/300
1N1614(A)	Si-Di	=1N1612: 200V	32a		BYX25/600, BYX99/300
1N1615(A)	Si-Di	=1N1612: 400V	32a		BYX25/600, BYX99/600
1N1616(A)	Si-Di	=1N1612: 600V	32a		BYX25/600, BYX99/600
1N1617	Si-Di	Gl, 100V, 1,5A	31a	Sem	BY251..255, BY226..227, 1N5392..99,++
1N1618	Si-Di	=1N1617: 200V	31a		BY251..255, BY226..227, 1N5393..99,++
1N1619	Si-Di	=1N1617: 300V	31a		BY252..255, BY226..227, 1N5394..99,++
1N1620	Si-Di	=1N1617: 400V	31a		BY252..255, BY226..227, 1N5395..99,++
1N1621	Si-Di	Gl-L, 100V, 10A(Tc=100°)	32a	Sem	BYX88/100, BYX76..81, 2N4506..11,++
1N1622	Si-Di	=1N1621: 200V	32a		BYW68/200, BYX77..61, 2N4506..11, ++
1N1623	Si-Di	=1N1621: 300V	32a		BYW88/300, BYX76..81, 2N4507..11, ++
1N1624	Si-Di	=1N1621: 400V	32a		BYW88/400, BYX76..81, 2N4507..11, ++
1N1625(A)	Se-Di	Gl, 48V, 0,25..0,5mA	≈36	Edl	—
1N1626(A)	Se-Di	Gl, 96V, 0,25..0,5mA	≈36	Edl	—
1N1627	Se-Di	Gl, 48V, 3,8mA	≈36	Edl	—
1N1628	Se-Di	Gl, 96V, 3,8mA	≈36	Edl	—
1N1629	Se-Di	Gl, 144V, 3,6mA	≈36	Edl	—
1N1630	Se-Di	Gl, 192V, 3,8mA	≈36	Edl	—
1N1631	Se-Di	Gl, 240V, 3,8mA	≈36	Edl	—
1N1632	Se-Di	Gl, 288V, 3,8mA	≈36	Edl	—
1N1633	Se-Di	Gl, 336V, 3,8mA	≈36	Edl	—
1N1634	Se-Di	Gl, 384V, 3,8mA	≈36	Edl	—
1N1635	Se-Di	Gl, 48V, 13mA	≈36	Edl	—
1N1636	Se-Di	Gl, 96V, 13mA	≈36	Edl	—
1N1637	Se-Di	Gl, 144V, 13mA	≈36	Edl	—
1N1638	Se-Di	Gl, 192V, 13mA	≈36	Edl	—
1N1639	Se-Di	Gl, 240V, 13mA	≈36	Edl	—
1N1640	Se-Di	Gl, 48V, 28mA	≈36	Edl	—
1N1641	Se-Di	Gl, 96V, 26mA	≈36	Edl	—
1N1642	Se-Di	Gl, 144V, 28mA	≈36	Edl	—
1N1644	Si-Di	Gl, 50V, 0,75A	34a	USA	BY126..127, BY133..135, 1N4001..07,++
1N1645	Si-Di	=1N1644: 100V	34a		BY126..127, BY133..135, 1N4002..07,++
1N1646	Si-Di	=1N1644: 150V	34a		BY126..127, BY133..134, 1N4003..07,++
1N1647	Si-Di	=1N1644: 200V	34a		BY126..127, BY133..134, 1N4003..07,++
1N1646	Si-Di	=1N1644: 250V	34e		BY126..127, BY133..134, 1N4004..07,++
1N1649	Si-Di	=1N1644: 300V	34a		BY126..127, BY133..134, 1N4004..07,++
1N1650	Si-Di	=1N1644: 350V	34a		BY126..127, BY133..134, 1N4004..07,++
1N1651	Si-Di	=1N1644: 400V	34a		BY126..127, BY133..134, 1N4004..07,++

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1N1652	Si-Di	=1N1644:500V	34a		BY126..127, BY133..134, 1N4005..07,++
1N1653	Si-Di	=1N1644:600V	34a		BY126..127, BY133..134, 1N4005..07,++
1N1660	Si-Di	GI-L, 50V, 116A(Tc=120°)	73a	USA	1N4587..96
1N1661	Si-Di	=1N1660:100V	73a		1N4587..96
1N1662	Si-Di	=1N1660:150V	73a		1N4588..96
1N1663	Si-Di	=1N1660:200V	73a		1N4588..96
1N1664	Si-Di	=1N1660:300V	73a		1N4589..96
1N1665	Si-Di	=1N1660:400V	73a		1N4590. 96
1N1666	Si-Di	=1N1660:500V	73a		1N4591..96
1N1670	Si-Di	GI-L, 50V, 240A(Tc=120°)	73a	Sem,Ssi	1N3735..44
1N1671	Si-Di	=1N1670:100V	73a		1N3735..44
1N1672	Si-Di	=1N1670:150V	73a		1N3736..44
1N1673	Si-Di	=1N1670:200V	73a		1N3736..44
1N1674	Si-Di	=1N1670:300V	73a		1N3737..44
1N1675	Si-Di	=1N1670:400V	73a		1N3736..44
1N1676	Si-Di	=1N1670:500V	73a		1N3739..44
1N1660	Si-Di	GI-L, 150V, 50A(Tc=150°)	73a	Ssi	1N3289..97
1N1681	Si-Di	=1N1660:250V	73a		1N3290..97
1N1662	Si-Di	=1N1660:300V	73a		1N3290..97
1N1683	Si-Di	=1N1660:350V	73a		1N3291..97
1N1664	Si-Di	=1N1660:400V	73a		1N3291..97
1N1685	Si-Di	=1N1660:450V	73a		1N3292..97
1N1696	Si-Di	=1N1660:500V	73a		1N3292..97
1N1687	Si-Di	=1N1660:600V	73a		1N3293..97
1N1688	Si-Di	=1N1660:700V	73a		1N3294..97
1N1689	Si-Di	=1N1660:800V	73a		1N3294..97
1N1690	Si-Di	=1N1660:900V	73a		1N3295..97
1N1691	Si-Di	=1N1680:1000V	73a		1N3295..97
1N1692	Si-Di	GI, 100V, 0,75A	34a	USA,Tix	BY126..127, BY133..135, 1N4002..07,++
1N1693	Si-Di	=1N1692:200V	34a		BY126..127, BY133..134, 1N4003..07,++
1N1694	Si-Di	=1N1692:300V	34a		BY126..127, BY133..134, 1N4004..07,++
1N1695	Si-Di	=1N1892:400V	34a		BY126..127, BY133..134, 1N4004..07,++
1N1696	Si-Di	=1N1692:500V	34a		BY126..127, BY133..134, 1N4005..07,++
1N1697	Si-Di	=1N1692:600V	34a		BY126..127, BY133..134, 1N4005..07,++
1N1696	Si-Di	kV-GI, 6,6kV, 0,062A	31a	Scn,Sem	1N5163..64
1N1699	Si-Di	kV-GI, 10kV, 0,058A	31a	Scn,Sem	1N5184
1N1700	Si-Di	kV-GI, 12kV, 0,05A	31a	Scn,Sem	1N3052
1N1701	Si-Di	GI, 50V, 0,3A	34a	USA	BA157..159, BY206..207, BY401..405,++
1N1702	Si-Di	=1N1701:100V	34a		BA157..159, BY206..207, BY402..405,++
1N1703	Si-Di	=1N1701:200V	34a		BA157..159, BY206..207, BY403..405,++
1N1704	Si-Di	=1N1701:300V	34a		BA157..159, BY206..207, BY404..405,++
1N1705	Si-Di	=1N1701:400V	34a		BA157..159, BY207, BY404..405,++
1N1706	Si-Di	=1N1701:500V	34a		BA158..159, BY207, BY405,++
1N1707	Si-Di	GI, 50V, 0,5A	34a	USA	BY126..127, BY133..135, 1N4001..07,++
1N1708	Si-Di	=1N1707:100V	34a		BY126..127, BY133..135, 1N4002..07,++
1N1709	Si-Di	=1N1707:200V	34a		BY126..127, BY133..134, 1N4003..07,++
1N1710	Si-Di	=1N1707:300V	34a		BY126..127, BY133..134, 1N4004..07,++
1N1711	Si-Di	=1N1707:400V	34a		BY126..127, BY133..134, 1N4004..07,++
1N1712	Si-Di	=1N1707:500V	34a		BY126..127, BY133..134, 1N4005..07,++
1N172	Di			Syl	—
1N173(A)	Di	UHF-M		USA	—
1N1730	Si-Di	kV-GI, 1kV, 0,2A	31a	Gen,Cie,Idc	GP02-20, HVG2, MR250-2
1N1730A	Si-Di	=1N1730:0,35A	31a	Mot,++	—
1N1731	Si-Di	kV-GI, 1,5kV, 0,2A	31a		GP02-20, HVG2, MR250-2
1N1731A	Si-Di	=1N1731:0,35A	31a		—
1N1732	Si-Di	kV-GI, 2kV, 0,2A	31a		GP02-20, HVG2, MR250-2
1N1732A	Si-Di	=1N1732:0,35A	31a		—
1N1733	6i-Di	kV-GI, 3kV, 0,2A	31a		GP02-30, HVG3, MR250-3
1N1733A	Si-Di	=1N1733:0,35A	31a		—
1N1734	Si-Di	kV-GI, 5kV, 0,2A	31a		HVG5, HP,250-5
1N1734A	Si-Di	=1N1734:0,35A	31a		—
1N1735(A)	Ref-Di	6,2V, 5%, 0,2W	31a	USA,Mot	BZV10..11, BZV27..28, 1N4560..81,++
1N1736(A)	Ref-Di	12,4V, 5%, 0,4W	31a	USA,Mo1	1N4908..09, 1N4912..13
1N1737(A)	Ref-Di	18,6V, 5%, 0,6W	31a	USA,Mot	—
1N1736(A)	Ral-Di	24,8V, 5%, 0,8W	31a	USA,Mo1	—
1N1739(A)	Ref-Di	31V, 5%, 1W	31a	USA,Mot	—

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1N174	Ge-Di			Del	—
1N1740(A)	Ref-Di	37,2V,5%,1,2W	31a	USA,Mot	—
1N1741(A)	Ref-Di	43,4V,5%,1,4W	31a	USA,Mot	—
1N1742(A)	Ref-Di	49,6V,5%,1,6W	31a	USA,Mot	—
1N1743	Z-Di	10V,5%,10W	32a	Wes	BZX98/C10, BZY93/C10, 1N2974
1N1744	Z-Di	10V,5%,1W	34a	Sem	BZW22/C10, BZX61/C10, ZPY10, 1N5925,++
1N1745	Si-Di	kV-Gl,1,5kV,0,38A	31a	USA	1N1731A
1N1746	Si-Di	kV-Gl,1,5kV,0,44A	31a	USA	—
1N1747	Si-Di	kV-Gl,1,8kV,0,36A	31a	USA	1N1732A
1N1748	Si-Di	kV-Gl,1,8kV,0,42A	31a	USA	—
1N1749	Si-Di	kV-Gl,2,4kV,0,23A	31a	USA	1N1733A
1N175	Ge-Di	Uni,125V,	31a	USA	AA133
1N1750	Si-Di	kV-Gl,2,4kV,0,38A	31a	USA	—
1N1751	Si-Di	kV-Gl,3,6kV,0,37A	31a	USA	1N1734A
1N1752	Si-Di	kV-Gl,3,6kV,0,36A	31a	USA	1N1734A
1N1753	Si-Di	kV-Gl,4,8kV,0,33A	31a	USA	1N1734A
1N1754	Si-Di	kV-Gl,4,8kV,0,32A	31a	USA	1N1734A
1N1755	Si-Di	kV-Gl,6kV,0,29A	31a	USA	—
1N1756	Si-Di	kV-Gl,6kV,0,36A	31a	USA	—
1N1757	Si-Di	kV-Gl,7,2kV,0,29A	31a	USA	—
1N1756	Si-Di	kV-Gl,7,2kV,0,33A	31a	USA	—
1N1759	Si-Di	kV-Gl,8kV,0,25A	31a	USA	—
1N1760	Si-Di	kV-Gl,12kV,0,25A	31a	USA	—
1N1761	Si-Di	kV-Gl,14kV,0,3A	31a	USA	—
1N1762	Si-Di	kV-Gl,16kV,0,25A	31a	USA	—
1N1763(A)	Si-Di	Gl,400V,0,5..1A	34a	USA,Rca	BY126..127, BY133..134, 1N4004..07,++
1N1764(A)	Si-Di	=1N1763: 500V	34a		BY126..127, BY133..134, 1N4005..07,++
1N1765	Z-Di	5,6V,10%,1W	34a	USA,Mot	BZW22/.., BZX61/.., ZPY.., 1M5919..56,++
1N1765A...1802A	Z-Di	=1N1765..1802: 5%	34a		—
1N1766	Z-Di	=1N1765: 6,2V	34a		—
1N1767	Z-Di	=1N1765: 6,8V	34a		—
1N1766	Z-Di	=1N1765: 7,5V	34a		—
1N1769	Z-Di	=1N1765: 8,2V	34a		—
1N1770	Z-Di	=1N1765: 9,1V	34a		—
1N1771	Z-Di	=1N1765: 10V	34a		—
1N1772	Z-Di	=1N1765: 11V	34a		—
1N1773	Z-Di	=1N1765: 12V	34a		—
1N1774	Z-Di	=1N1765: 13V	34a		—
1N1775	Z-Di	=1N1765: 15V	34a		—
1N1776	Z-Di	=1N1765: 16V	34a		—
1N1777	Z-Di	=1N1765: 18V	34a		—
1N1778	Z-Di	=1N1765: 20V	34a		—
1N1779	Z-Di	=1N1765: 22V	34a		—
1N1760	Z-Di	=1N1765: 24V	34a		—
1N1781	Z-Di	=1N1765: 27V	34a		—
1N1782	Z-Di	=1N1765: 30V	34a		—
1N1763	Z-Di	=1N1765: 33V	34a		—
1N1784	Z-Di	=1N1765: 36V	34a		—
1N1785	Z-Di	=1N1765: 39V	34a		—
1N1786	Z-Di	=1N1765: 43V	34a		—
1N1787	Z-Di	=1N1765: 47V	34a		—
1N1788	Z-Di	=1N1765: 51V	34a		—
1N1769	Z-Di	=1N1765: 56V	34a		—
1N1790	Z-Di	=1N1765: 62V	34a		—
1N1791	Z-Di	=1N1765: 66V	34a		—
1N1792	Z-Di	=1N1765: 75V	34a		—
1N1793	Z-Di	=1N1765: 82V	34a		—
1N1794	Z-Di	=1N1765: 91V	34a		—
1N1795	Z-Di	=1N1765: 100V	34a		—
1N1796	Z-Di	=1N1765: 110V	34a		—
1N1797	Z-Di	=1N1765: 120V	34a		—
1N1798	Z-Di	=1N1765: 130V	34a		—
1N1799	Z-Di	=1N1765: 150V	34a		—
1N1800	Z-Di	=1N1765: 160V	34a		—
1N1601	Z-Di	=1N1765: 180V	34a		—
1N1802	Z-Di	=1N1765: 200V	34a		—

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1N1803	Z-Di	5,6V, 10%, 10W	32b	USA,Mot,Sie	BZX98/.., BZY93/.., 1N2970..3015
1N1803A..1815A	Z-Di	=1N1803..1815: 5%	32b		—
1N1803B..1815B	Z-Di	=1N1803..1815: 20%	32b		—
1N1803C..1815C	Z-Di	=1N1803..1815: bidirektional	32b		—
1N1803CA..1815CA	Z-Di	=1N1803..1815: bidirektional, 5%	32b		—
1N1803R..1815R	Z-Di	=1N1803..1815:	32a		—
1N1804	Z-Di	=1N1803: 6,2V	32b		—
1N1805	Z-Di	=1N1803: 6,8V	32b		—
1N1806	Z-Di	=1N1803: 7,5V	32b		—
1N1807	Z-Di	=1N1803: 8,2V	32b		—
1N1808	Z-Di	=1N1803: 9,1V	32b		—
1N1809	Z-Di	=1N1803: 110V	32b		—
1N1810	Z-Di	=1N1803: 120V	32b		—
1N1811	Z-Di	=1N1803: 130V	32b		—
1N1812	Z-Di	=1N1803: 150V	32b		—
1N1813	Z-Di	=1N1803: 160V	32b		—
1N1814	Z-Di	=1N1803: 180V	32b		—
1N1815	Z-Di	=1N1803: 200V	32b		—
1N1816	Z-Di	13V, 10%, 10W	32b	USA,Mot,Sie	BZX98/.., BZY93/.., 1N2977..3004
1N1816A..1836A	Z-Di	=1N1816..1836: 5%	32b		—
1N1816C..1836C	Z-Di	=1N1816..1836: bidirektional	32b		—
1N1816CA..1836C+A1807A	Z-Di	=1N1816..1836: bidirektional, 5%	32b		—
1N1816R..1836R	Z-Di	=1N1816..1836:	32a		—
1N1817	Z-Di	=1N1816: 15V	32b		—
1N1818	Z-Di	=1N1816: 16V	32b		—
1N1819	Z-Di	=1N1816: 18V	32b		—
1N1820	Z-Di	=1N1816: 20V	32b		—
1N1821	Z-Di	=1N1816: 22V	32b		—
1N1822	Z-Di	=1N1816: 24V	32b		—
1N1823	Z-Di	=1N1816: 27V	32b		—
1N1824	Z-Di	=1N1816: 30V	32b		—
1N1825	Z-Di	=1N1816: 33V	32b		—
1N1826	Z-Di	=1N1816: 36V	32b		—
1N1827	Z-Di	=1N1816: 36V	32b		—
1N1828	Z-Di	=1N1816: 43V	32b		—
1N1829	Z-Di	=1N1816: 47V	32b		—
1N1830	Z-Di	=1N1816: 51V	32b		—
1N1831	Z-Di	=1N1816: 56V	32b		—
1N1832	Z-Di	=1N1816: 62V	32b		—
1N1833	Z-Di	=1N1816: 68V	32b		—
1N1834	Z-Di	=1N1816: 75V	32b		—
1N1835	Z-Di	=1N1816: 82V	32b		—
1N1836	Z-Di	=1N1816: 91V	32b		—
1N1838	Ge-Di	UHF, X/Ku-Band-M	Koax	USA	—
1N1839	Si-Di	Gl, 6,8V, 85mA	2c	USA	—
1N1840	Si-Di	Gl, 10V, 77mA	2c	USA	—
1N1841	Si-Di	Gl, 15V, 63mA	2c	USA	—
1N1842	Si-Di	Gl, 22V, 50mA	2c	USA	—
1N1843	Si-Di	Gl, 33V, 40mA	2c	USA	—
1N1844	Si-Di	Gl, 47V, 30mA	2c	USA	—
1N1845	Si-Di	Gl, 68V, 23mA	2c	USA	—
1N1846	Si-Di	Gl, 100V, 16mA	2c	USA	—
1N1847	Si-Di	Gl, 150V, 11mA	2c	USA	—
1N1848	Si-Di	Gl, 330V, 7,5mA	2c	USA	—
1N1850	Si-Di	Gl, 470V, 6mA	2c	USA	—
1N1851	Si-Di	≈1N1839			—
1N1852	Si-Di	≈1N1840			—
1N1853	Si-Di	≈1N1841			—
1N1854	Si-Di	≈1N1842			—
1N1855	Si-Di	≈1N1843			—
1N1856	Si-Di	≈1N1844			—
1N1857	Si-Di	≈1N1845			—
1N1858	Si-Di	≈1N1846			—
1N1859	Si-Di	≈1N1847			—
1N1860	Si-Di	≈1N1848			—
1N1861	Si-Di	≈1N1849			—

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1N1862	Si-Di	≈1N1850			—
1N1863	Si-Di	≈1N1839			—
1N1864	Si-Di	≈1N1840			—
1N1865	Si-Di	≈1N1841			—
1N1866	Si-Di	≈1N1842			—
1N1867	Si-Di	≈1N1643			—
1N1868	Si-Di	≈1N1844			—
1N1869	Si-Di	≈1N1845			—
1N1870	Si-Di	≈1N1846			—
1N1871	Si-Di	≈1N1847			—
1N1872	Si-Di	≈1N1846			—
1N1873	Si-Di	≈1N1849			—
1N1874	Si-Di	≈1N1850			—
1N1875	Z-Di	8,2V, 10%, 1W	34a	USA	BZW22/.., BZX61/.., ZPY.., 1N5923..49,++
1N1875A...1888A	Z-Di	=1N1875..1668: 5%	34a		—
1N1875B...1866B	Z-Di	=1N1875..1668: 1%	34a		—
1N1876	Z-Di	=1N1875: 10V	34a		—
1N1877	Z-Di	=1N1875: 12V	34a		—
1N1878	Z-Di	=1N1875: 15V	34a		—
1N1879	Z-Di	=1N1875: 18V	34a		—
1N166	Opto				—
1N1880	Z-Di	=1N1875: 22V	34a		—
1N1881	Z-Di	=1N1875: 27V	34a		—
1N1882	Z-Di	=1N1875: 33V	34a		—
1N1883	Z-Di	=1N1875: 39V	34a		—
1N1864	Z-Di	=1N1875: 47V	34a		—
1N1885	Z-Di	=1N1875: 56V	34a		—
1N1866	Z-Di	=1N1875: 66V	34a		—
1N1887	Z-Di	=1N1875: 82V	34a		—
1N1888	Z-Di	=1N1875: 100V	34a		—
1N1889	Z-Di	120V, 10%, 3W	32a	USA	BZX98/.., BZY93/.., 1N3008..3011
1N1889A...1890A	Z-Di	≈1N1669..1890: 5%	32a		—
1N1669B....1890B	Z-Di	=1N1889..1890: 1%	32a		—
1N189	Opto				—
1N1890	Z-Di	=1N1669: 145V	32a		—
1N1891	Z-Di	8,2V, 10%, 10W	32	Idc,Ssi	BZX98/.., BZY93/.., 1N2972..3011
1N1891A...1906A	Z-Di	≈1N1691..1908: 5%	32		—
1N1892	Z-Di	≈1N1891: 10V	32		—
1N1893	Z-Di	=1N1891: 12V	32		—
1N1894	Z-Di	≈1N1891: 15V	32		—
1N1895	Z-Di	=1N1891: 18V	32		—
1N1896	Z-Di	=1N1891: 22V	32		—
1N1897	Z-Di	=1N1891: 27V	32		—
1N1896	Z-Di	=1N1891: 33V	32		—
1N1899	Z-Di	=1N1891: 39V	32		—
1N190	Ge-Di	3V			—
1N1900	Z-Di	=1N1891: 47V	32		—
1N1901	Z-Di	=1N1891: 56V	32		—
1N1902	Z-Di	=1N1891: 66V	32		—
1N1903	Z-Di	=1N1891: 92V	32		—
1N1904	Z-Di	=1N1891: 100V	32		—
1N1905	Z-Di	=1N1891: 120V	32		—
1N1906	Z-Di	=1N1891: 150V	32		—
1N1907	Si-Di	Gl, 50V, 1,5A	34a	USA	BY251..255, BY226..227, 1N5391..99,++
1N1906	Si-Di	=1N1907: 100V	34a		BY251..255, BY226..227, 1N5392..99,++
1N1909	Si-Di	=1N1907: 200V	34a		BY251..255, BY226..227, 1N5393..99,++
1N191	Ge-Di	S, 90V, 30mA, <100ns	31a	USA,Tho	AAY 26
1N1910	Si-Di	=1N1907: 300V	34a		BY252..255, BY226..227, 1N5394..99,++
1N1911	Si-Di	=1N1907: 400V	34a		BY252..255, BY226..227, 1N5395..99,++
1N1912	Si-Di	=1N1907: 500V	34a		BY253..255, BY226..227, 1N5396..99,++
1N1913	Si-Di	=1N1907: 600V	34a		BY253..255, BY226..227, 1N5397..99,++
1N1914	Si-Di	=1N1907: 700V	34a		BY254..255, BY227, 1N5398..99,++
1N1915	Si-Di	=1N1907: 800V	34a		BY254..255, BY227, 1N5399,++
1N1916	Si-Di	=1N1907: 900V	34a		BY255, BY227, BYW55, GP15M,++
1N1917	Si-Di	Gl-L, 50V, 4A	32	Idc,Ssi	BYX38/300, BYX39/600
1N1918	Si-Di	=1N1917: 100V	32		BYX38/300, BYX39/600

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1N1919	Si-Di	=1N1917:200V	32		BYX38/300, BYX39/600
1N192	Ge-Di	=1N191:70V	31a	USA,Tho	AAY28
1N1920	Si-Di	=1N1917:300V	32		BYX38/300, BYX39/600
1N1921	Si-Di	=1N1917:400V	32		BYX38/600, BYX39/600
1N1922	Si-Di	=1N1917:500V	32		BYX38/600, BYX39/600
1N1923	Si-Di	=1N1917:600V	32		BYX38/600, BYX39/600
1N1924	Si-Di	=1N1917:700V	32		BYX38/900, BYX39/800
1N1925	Si-Di	=1N1917:800V	32		BYX38/900, BYX39/800
1N1928	Si-Di	=1N1917:900V	32		BYX38/900, BYX39/1000
1N1927	Z-Di	3,9V, 10%, 0,2W	34a	USA	BZX55/.., BZX79/.., ZPD.., 1N5228..71,++
1N1927A..1944A	Z-Di	=1N1927..1944:5%	34a		—
1N1927B..1944B	Z-Di	=1N1927..1944:1%	34a		—
1N1928	Z-Di	=1N1927:4,7V	34a		—
1N1929	Z-Di	=1N1927:5,6V	34a		—
1N193	Si-Di	40V, <500ns		Syl	—
1N1930	Z-Di	=1N1927:6,8V	34a		—
1N1931	Z-Di	=1N1927:8,2V	34a		—
1N1932	Z-Di	=1N1927:10V	34a		—
1N1933	Z-Di	=1N1927:12V	34a		—
1N1934	Z-Di	=1N1927:15V	34a		—
1N1935	Z-Di	=1N1927:18V	34a		—
1N1936	Z-Di	=1N1927:22V	34a		—
1N1937	Z-Di	=1N1927:27V	34a		—
1N1936	Z-Di	=1N1927:33V	34a		—
1N1939	Z-Di	=1N1927:39V	34a		—
1N194(A)	Si-Di	S, 40V, 30mA, 200ns	31a	USA	BAV18..21, BAX15..17, 1N4148,++
1N1940	Z-Di	=1N1927:47V	34a		—
1N1941	Z-Di	=1N1927:56V	34a		—
1N1942	Z-Di	=1N1927:68V	34a		—
1N1943	Z-Di	=1N1927:82V	34a		—
1N1944	Z-Di	=1N1927:100V	34a		—
1N1945	Z-Di	120V, 10%, 0,2W	31a	USA	BZX55/.., BZX79/.., ZPD.., 1N5273..81,..
1N1945A..1953A	Z-Di	=1N1945..1953:5%	31a		—
1N1945B..1953B	Z-Di	=1N1945..1953:1%	31a		—
1N1946	Z-Di	=1N1945:145V	31a		—
1N1947	Z-Di	=1N1945:180V	31a		—
1N1948	Z-Di	=1N1945:220V	31a		—
1N1949	Z-Di	=1N1945:270V	31a		—
1N195	Si-Di	S, 40V, 30mA, 300ns	31a	USA	BAV18..21, BAX15..17, 1N4148,++
1N1950	Z-Di	=1N1945:330V	31a		—
1N1951	Z-Di	=1N1945:395V	31a		—
1N1952	Z-Di	=1N1945:470V	31a		—
1N1953	Z-Di	=1N1945:565V	31a		—
1N1954	Z-Di	3,95V, 10%, 0,4W	31a	USA	BZX55/.., BZX83/.., ZPD.., 1N5228..57,++
1N1954A..1965A	Z-Di	=1N1954..1965:5%	31a		—
1N1954B..1965B	Z-Di	=1N1954..1965:1%	31a		—
1N1955	Z-Di	=1N1954:4,7V	31a		—
1N1956	Z-Di	=1N1954:5,65V	31a		—
1N1957	Z-Di	=1N1954:6,85V	31a		—
1N1956	Z-Di	=1N1954:8,3V	31a		—
1N1959	Z-Di	=1N1954:9,7V	31a		—
1N196	Si-Di	S, 40V, 30mA, 100ns	31a	USA	BAV18..21, BAX15..17, 1N4148,++
1N1960	Z-Di	=1N1954:12V	31a		—
1N1961	Z-Di	=1N1954:14,5V	31a		—
1N1962	Z-Di	=1N1954:18V	31a		—
1N1963	Z-Di	=1N1954:22V	31a		—
1N1964	Z-Di	=1N1954:27V	31a		—
1N1965	Z-Di	=1N1954:33V	31a		—
1N1966	Z-Di	39,5V, 10%, 0,4W	34a	Sem	BZX55/.., BZX83/.., ZPD.., 1N5259..81,++
1N1967	Z-Di	=1N1966:47V	34a		—
1N1968	Z-Di	=1N1968:58,5V	34a		—
1N1969	Z-Di	=1N1968:68,5V	34a		—
1N197	Si-Di	≈2x1N21			—
1N1970	Z-Di	=1N1966:83V	34a		—
1N1971	Z-Di	=1N1966:100V	34a		—
1N1972	Z-Di	=1N1966:120V	34a		—

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1N1973	Z-Di	=1N1966: 150V	34a		—
1N1974	Z-Di	=1N1966: 180V	34a		—
1N1975	Z-Di	=1N1966: 220V	34a		—
1N1976	Z-Di	=1N1966: 270V	34a		—
1N1977	Z-Di	=1N1966: 330V	34a		—
1N1978	Z-Di	=1N1966: 390V	34a		—
1N1979	Z-Di	=1N1966: 470V	34a		—
1N198(A...N)	Ge-Di	Uni, S, 100V, 30mA, <300ns	31a	USA, Tho	AAY28, 1N191
1N1980	Z-Di	=1N1966: 560V	34a		—
1N1981	Z-Di	3,9V, 10%, 0,15W	2c	USA	BZX55/.., BZX79/.., ZPD.., 1N5228..81, ++
1N1981A...2007A	Z-Di	=1N1981..2007: 5%	2c		—
1N1981B...2007B	Z-Di	=1N1981..2007: 1%	2c		—
1N1982	Z-Di	=1N1981: 4,7V	2c		—
1N1983	Z-Di	=1N1981: 5,6V	2c		—
1N1984	Z-Di	=1N1981: 6,8V	2c		—
1N1985	Z-Di	=1N1981: 8,2V	2c		—
1N1998	Z-Di	=1N1981: 10V	2c		—
1N1987	Z-Di	=1N1981: 12V	2c		—
1N1988	Z-Di	=1N1981: 15V	2c		—
1N1989	Z-Di	=1N1981: 18V	2c		—
1N1990	Z-Di	=1N1981: 22V	2c		—
1N1991	Z-Di	=1N1981: 27V	2c		—
1N1992	Z-Di	=1N1981: 33V	2c		—
1N1993	Z-Di	=1N1981: 39V	2c		—
1N1994	Z-Di	=1N1981: 47V	2c		—
1N1995	Z-Di	=1N1981: 56V	2c		—
1N1998	Z-Di	=1N1981: 68V	2c		—
1N1997	Z-Di	=1N1981: 82V	2c		—
1N1998	Z-Di	=1N1981: 100V	2c		—
1N1999	Z-Di	=1N1981: 120V	2c		—
1N200	Z-Di	8,8V, 10%, 0,15W	2c	USA	BZX55/.., BZX79/.., ZPD..F2041, 1N5235..81, ++
1N2000	Z-Di	=1N1981: 150V	2c		—
1N2001	Z-Di	=1N1981: 180V	2c		—
1N2002	Z-Di	=1N1981: 220V	2c		—
1N2003	Z-Di	=1N1981: 270V	2c		—
1N2004	Z-Di	=1N1981: 330V	2c		—
1N2005	Z-Di	=1N1981: 390V	2c		—
1N2006	Z-Di	=1N1981: 470V	2c		—
1N2007	Z-Di	=1N1981: 560V	2c		—
1N2006	Z-Di	100V, 10%, 10W	32b	USA, Mot, Sie	BZX98/.., BZY93/.., 1N3005..3011
1N2008A...2012A	Z-Di	=1N2006..2012: 5%	32b		—
1N2008C...2012C	Z-Di	=1N2008..2012: bidirektional	32b		—
1N2008CA...2012CA	Z-Di	=1N2008..2012: bidirektional, 5%	32b		—
1N2008R...2012R	Z-Di	=1N2008..2012:	32a		—
1N2009	Z-Di	=1N2008: 110V	32b		—
1N201	Z-Di	=1N200: 8,2V	2c		—
1N2010	Z-Di	=1N2008: 120V	32b		—
1N2011	Z-Di	=1N2008: 130V	32b		—
1N2012	Z-Di	=1N2008: 150V	32b		—
1N2013	Si-Di	Gl, 50V, 0,2A	34a	USA	BA157..159, BY208..207, BY204/4, ++
1N2014	Si-Di	=1N2013: 100V	34a		BA157..159, BY206..207, BY204/4, ++
1N2015	Si-Di	=1N2013: 150V	34a		BA157..159, BY206..207, BY204/4, ++
1N2016	Si-Di	=1N2013: 200V	34a		BA157..159, BY206..207, BY204/4, ++
1N2017	Si-Di	=1N2013: 250V	34a		BA157..159, BY206..207, BY204/4, ++
1N2018	Si-Di	=1N2013: 300V	34a		BA157..159, BY206..207, BY204/4, ++
1N2019	Si-Di	=1N2013: 350V	34a		BA157..159, BY206..207, BY204/4, ++
1N202	Z-Di	=1N200: 10V	2c		—
1N2020	Si-Di	=1N2013: 400V	34a		BA157..159, BY207, BY204/4, ++
1N2021	Si-Di	Gl-L, 150V, 10A(Tc=150°)	32a	USA	BYW88/200, BYX42/300, BYX77..81, ++
1N2022	Si-Di	=1N2021: 250V	32a		BYW88/300, BYX42/300, BYX78..81, ++
1N2023	Si-Di	=1N2021: 300V	32a		BYW88/300, BYX42/300, BYX76..81, ++
1N2024	Si-Di	=1N2021: 350V	32a		BYW88/400, BYX42/600, BYX78..81, ++
1N2025	Si-Di	=1N2021: 400V	32a		BYW88/400, BYX42/600, BYX76..81, ++
1N2026	Si-Di	Gl-L, 50V, 1A(Tc=150°)	32a	USA	BYX38/300, BYX39/600
1N2027	Si-Di	=1N2026: 200V	32a		BYX38/300, BYX39/600
1N2028	Si-Di	=1N2026: 300V	32a		BYX38/300, BYX39/600

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1N2029	Si-Di	=1N2026: 400V	32a		BYX38/600, BYX39/600
1N203	Z-Di	=1N200: 12V	2c		—
1N2030	Si-Di	=1N2026: 500V	32a		BYX38/600, BYX39/600
1N2031	Si-Di	=1N2026: 600V	32a		BYX38/600, BYX39/600
1N2032	Z-Di	4,65V, 10%, 0,75W	34a	USA,Mot	BZV65/.., BZW22/.., ZPY.., 1N3016..29,++
1N2032A...2040A	Z-Di	=1N2032..2040: 5%	34a		—
1N2033	Z-Di	=1N2032: 5,6V	34a		—
1N2034	Z-Di	=1N2032: 7,1V	34a		—
1N2035	Z-Di	=1N2032: 6,75V	34a		—
1N2036	Z-Di	=1N2032: 10,5V	34a		—
1N2037	Z-Di	=1N2032: 12,7V	34a		—
1N2038	Z-Di	=1N2032: 15,7V	34a		—
1N2039	Z-Di	=1N2032: 19V	34a		—
1N204	Z-Di	=1N200: 15V	2c		—
1N2040	Z-Di	=1N2032: 23,5V	34a		—
1N2041	Z-Di	4,65V, 10%, 10W	32	USA,Mot,Sie	BZX98/..,BZY93/.., 1N2970..86
1N2041...49A..D	Z-Di	=1N2041..2049: ≈5%	32		—
1N2041..49-1..-4	Z-Di	=1N2041..2049: ≈5%	32		—
1N2042	Z-Di	=1N2041: 5,6V	32		—
1N2043	Z-Di	=1N2041: 7,1V	32		—
1N2044	Z-Di	=1N2041: 6,75V	32		—
1N2045	Z-Di	=1N2041: 10,5V	32		—
1N2046	Z-Di	=1N2041: 12,7V	32		—
1N2047	Z-Di	=1N2041: 15,7V	32		—
1N2048	Z-Di	=1N2041: 19V	32		—
1N2049	Z-Di	=1N2041: 23,5V	32		—
1N205	Z-Di	=1N200: 16V	2c		—
1N2054	Si-Di	Gl-L, 50V, 250A(Tc=135°)	73a	USA	1N3735..44
1N2055	Si-Di	=1N2054: 100V	73a		1N3735..44
1N2056	Si-Di	=1N2054: 150V	73a		1N3736..44
1N2057	Si-Di	=1N2054: 200V	73a		1N3736..44
1N2058	Si-Di	=1N2054: 250V	73a		1N3737..44
1N2059	Si-Di	=1N2054: 300V	73a		1N3737..44
1N206	Z-Di	=1N200: 22V	2c		—
1N2060	Si-Di	=1N2054: 350V	73a		1N3738..44
1N2061	Si-Di	=1N2054: 400V	73a		1N3738..44
1N2062	Si-Di	=1N2054: 450V	73a		1N3739..44
1N2063	Si-Di	=1N2054: 500V	73a		1N3739..44
1N2064	Si-Di	=1N2054: 600V	73a		1N3740..44
1N2065	Si-Di	=1N2054: 700V	73a		1N3741..44
1N2066	Si-Di	=1N2054: 800V	73a		1N3741..44
1N2067	Si-Di	=1N2054: 900V	73a		1N3742..44
1N2068	Si-Di	=1N2054: 1000V	73a		1N3742..44
1N2069(A)	Si-Di	Gl, Uni, 200V, 0,75A	31a	Gie,Tix,++	BY126..127, BY133..134, 1N4003..07,++
1N207	Z-Di	=1N200: 27V	2c		—
1N2070(A)	Si-Di	=1N2069: 400V	31a		BY126..127, BY133..134, 1N4004..07,++
1N2071(A)	Si-Di	=1N2069: 600V	31a		BY126..127, BY133..134, 1N4005..07,++
1N2072	Si-Di	Gl, 50V, 0,75A	34a	USA	BY126..127, BY133..135, 1N4001..07,++
1N2073	Si-Di	=1N2072: 100V	34a		BY126..127, BY133..135, 1N4002..07,++
1N2074	Si-Di	=1N2072: 150V	34a		BY126..127, BY133..135, 1N4003..07,++
1N2075	Si-Di	=1N2072: 200V	34a		BY126..127, BY133..134, 1N4003..07,++
1N2076	Si-Di	=1N2072: 250V	34a		BY126..127, BY133..134, 1N4004..07,++
1N2077	Si-Di	=1N2072: 300V	34a		BY126..127, BY133..134, 1N4004..07,++
1N2078	Si-Di	=1N2072: 400V	34a		BY126..127, BY133..134, 1N4004..07,++
1N2079	Si-Di	=1N2072: 500V	34a		BY126..127, BY133..134, 1N4005..07,++
1N208	Z-Di	=1N200: 33V	2c		—
1N2080	Si-Di	Gl, 50V, 0,5A	34a	USA	BY126..127, BY133..135, 1N4001..07,++
1N2081	Si-Di	=1N2080: 100V	34a		BY126..127, BY133..135, 1N4002..07,++
1N2082	Si-Di	=1N2080: 200V	34a		BY126..127, BY133..134, 1N4003..07,++
1N2083	Si-Di	=1N2080: 300V	34a		BY126..127, BY133..134, 1N4004..07,++
1N2084	Si-Di	=1N2080: 400V	34a		BY126..127, BY133..134, 1N4004..07,++
1N2085	Si-Di	=1N2080: 500V	34a		BY126..127, BY133..134, 1N4005..07,++
1N2086	Si-Di	=1N2080: 600V	34a		BY126..127, BY133..134, 1N4005..07,++
1N2088	Si-Di	Gl, 500V, 0,75A			BY126..127, BY133..134, 1N4005..07,++
1N2089	Si-Di	=1N2088: 600V			BY126..127, BY133..134, 1N4005..07,++
1N209	Z-Di	=1N200: 39V	2c		—

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1N2090	Si-Di	Gl, 50V, 0,75A	≈36a	USA	BY126..127, BY133..135, 1N4001..07,++
1N2091	Si-Di	=1N2090: 100V	≈36a		BY126..127, BY133..135, 1N4002..07,++
1N2092	Si-Di	=1N2090: 200V	≈36a		BY126..127, BY133..134, 1N4003..07,++
1N2093	Si-Di	=1N2090: 300V	≈36a		BY126..127, BY133..134, 1N4004..07,++
1N2094	Si-Di	=1N2090: 400V	≈36a		BY126..127, BY133..134, 1N4004..07,++
1N2095	Si-Di	=1N2090: 500V	≈36a		BY126..127, BY133..134, 1N4005..07,++
1N2096	Si-Di	=1N2090: 600V	≈36a		BY126..127, BY133..134, 1N4005..07,++
1N21	Si-Di	UHF, S-Band-M	Koax	Nec, Tho, ++	—
1N210	Z-Di	=1N200: 47V	2c		—
1N2102	Si-Di	UHF, L/S-Band-Dem	Koax	USA	—
1N2103	Si-Di	Gl, 50V, 0,75A	34a	USA	BY126..127, BY133..135, 1N4001..07,++
1N2104	Si-Di	=1N2103: 100V	34a		BY126..127, BY133..135, 1N4002..07,++
1N2105	Si-Di	=1N2103: 200V	34a		BY126..127, BY133..134, 1N4003..07,++
1N2106	Si-Di	=1N2103: 300V	34a		BY126..127, BY133..134, 1N4004..07,++
1N2107	Si-Di	=1N2103: 400V	34a		BY126..127, BY133..134, 1N4004..07,++
1N2108	Si-Di	=1N2103: 500V	34a		BY126..127, BY133..134, 1N4005..07,++
1N2109	Si-Di	Gl-L, 50V, 2A	32	Idc, Sem	(BY249/300, BYX38/300, BYX39/600,++)
1N211	Z-Di	=1N200: 56V	2c		—
1N2110	Si-Di	=1N2109: 100V	32		(BY249/300, BYX38/300, BYX39/600,++)
1N2111	Si-Di	=1N2109: 200V	32		(BY249/300, BYX38/300, BYX39/600,++)
1N2112	Si-Di	=1N2109: 300V	32		(BY249/300, BYX38/300, BYX39/600,++)
1N2113	Si-Di	=1N2109: 400V	32		(BY249/600, BYX38/600, BYX39/600,++)
1N2114	Si-Di	=1N2109: 500V	32		(BY249/600, BYX38/600, BYX39/600,++)
1N2115	Si-Di	Gl, 365V, 0,3A	≈36a	USA	BA157..159, BY206..207, BY204/4,++
1N2116	Si-Di	Gl, 400V, 0,75A	34a	USA	BY126..127, BY133..134, 1N4004..07,++
1N2117	Si-Di	Gl, 720V, 0,75A	34a	USA	BY127, BY133, BYW42, 1N4006..07,++
1N212	Z-Di	=1N200: 66V	2c		—
1N2127(A)	Si-Di	UHF, L/X-Band-Dem	Koax	USA	—
1N2128	Si-Di	Gl-L, 50V, 60A(Tc=115°)	32a	USA	—
1N2128R...2138A	Si-Di	=1N2128..2138: 60A(Tc=140°)	32a		—
1N2128R...2138R	Si-Di	=1N2128..2138:	32b		DS75-02B..-16B
1N2129	Si-Di	=1N2128: 100V	32a		—
1N213	Z-Di	=1N200: 82V	2c		—
1N2130	Si-Di	=1N2128: 150V	32a		—
1N2131	Si-Di	=1N2128: 200V	32a		—
1N2132	Si-Di	=1N2128: 250V	32a		—
1N2133	Si-Di	=1N2128: 300V	32a		—
1N2134	Si-Di	=1N2128: 350V	32a		—
1N2135	Si-Di	=1N2128: 400V	32a		—
1N2136	Si-Di	=1N2128: 450V	32a		—
1N2137	Si-Di	=1N2128: 500V	32a		—
1N2138	Si-Di	=1N2128: 600V	32a		—
1N2139	Si-Di	kV-Gl, 20kV, 0,045A	31a	USA	1N3057
1N214	Z-Di	=1N200: 100V	2c		—
1N2146	Si-Di	Gl, S, 120V, <50ns	34a	Wes	SAV15..16, EGP10C, FE1C
1N2147(A)	Si-Di	Gl-L, 50V, 6A(Tc=150°)	32a	USA	BYX38/300, BYX39/600
1N2148(A)	Si-Di	=1N2147: 100V	32a		BYX38/300, BYX39/600
1N2149(A)	Si-Di	=1N2147: 200V	32a		BYX38/300, BYX39/600
1N215	Z-Di	=1N200: 120V	2c		—
1N2150(A)	Si-Di	=1N2147: 300V	32a		BYX38/300, BYX39/600
1N2151(A)	Si-Di	=1N2147: 400V	32a		BYX38/600, BYX39/600
1N2152(A)	Si-Di	=1N2147: 500V	32a		BYX38/600, BYX39/600
1N2153(A)	Si-Di	=1N2147: 600V	32a		BYX38/600, BYX, 39/600
1N2154	Si-Di	Gl-L, 50V, 25A(Tc=145°)	32a	USA	1N3765..68, 1N4525..30
1N2154R...2160R	Si-Di	=1N2154..2160:	32b		1N3765R..68R
1N2155	Si-Di	=1N2154: 100V	32a		1N3765..68, 1N4525..30
1N2156	Si-Di	=1N2154: 200V	32a		1N3765..68, 1N4525..30
1N2157	Si-Di	=1N2154: 300V	32a		1N3765..68, 1N4526..30
1N2158	Si-Di	=1N2154: 400V	32a		1N3765..66, 1N4526..30
1N2159	Si-Di	=1N2154: 500V	32a		1N3765..68, 1N4527..30
1N216	Z-Di	=1N200: 150V	2c		—
1N2160	Si-Di	=1N2154: 600V	32a		1N3765..68, 1N4527..30
1N2163(A)	Ref-Di	9,4V, 0,75W	34a	USA, Mot, Sie	—
1N2164(A)	Ref-Di	9,4V, 0,75W	34a		—
1N2165(A)	Ref-Di	9,4V, 0,75W	34a		—
1N2166(A)	Ref-Di	9,4V, 0,75W	34a		—

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1N2167(A)	Ref-Di	9,4V,0,75W	34a		—
1N2168(A)	Ref-Di	9,4V,0,75W	34a		—
1N2168(A)	Ref-Di	9,4V,0,75W	34a		—
1N217	Z-Di	=1N200: 180V	2c		—
1N2170(A)	Ref-Di	9,4V,0,75W	34a		—
1N2171(A)	Ref-Di	9,4V,0,75W	34a		—
1N2172	Si-Di	GI-L,50V,50A(Tc=150°)	73a	USA	1N3288..97
1N2173	Si-Di	=1N2172: 100V	73a		1N3288..97
1N2174	Si-Di	=1N2172: 200V	73a		1N3289..97
1N2175	Opto				—
1N2176	Si-Di	GI,50V,3A			BY251..255, BYW82, GP30A, 1N5400..08,++
1N2177	Si-Di	=1N2176: 100V			BY251..255, BYW62, GP30B, 1N5401..08,++
1N2178	Si-Di	=1N2176: 150V			BY251..255, BYW62, GP30D, 1N5402..08,++
1N2179	Si-Di	=1N2176: 200V			BY251..255, BYW82, GP30D, 1N5402..08,++
1N216	Z-Di	=1N200: 220V	2c		—
1N2180	Si-Di	=1N2176: 300V			BY252..255, BYW83, GP30G, 1N5403..06,++
1N2181	Si-Di	=1N2176: 400V			BY252..255, BYW83, GP30G, 1N5404..08,++
1N2182	Si-Di	=1N2176: 500V			BY253..255, BYW84, GP30J, 1N5405..08,++
1N2183	Si-Di	=1N2176: 600V			BY253..255, BYW84, GP30J, 1N5406..08,++
1N2184	Si-Di	GI,50V,3A			BY251..255, BYW82,GP30A, 1N5400..08,++
1N2185	Si-Di	=1N2184: 100V			BY251..255, BYW82,GP30B, 1N5401..08,++
1N2186	Si-Di	=1N2184: 150V			BY251..255, BYW82,GP30D, 1N5402..08,++
1N2187	Si-Di	=1N2184: 200V			BY251..255, BYW82,GP30D, 1N5402..08,++
1N2188	Si-Di	=1N2184: 300V			BY252..255, BYW83, GP30G, 1N5403..06,++
1N2189	Si-Di	=1N2184: 400V			BY252..255, BYW83, GP30G, 1N5404..08,++
1N219	Z-Di	=1N200: 270V	2c		—
1N2190	Si-Di	=1N2184: 500V			BY253..255, BYW84, GP30J, 1N5405..08,++
1N2191	Si-Di	=1N2184: 600V			BY253..255, BYW84, GP30J, 1N5406..08,++
1N2192	Si-Di	=1N2184: 600V			BY254..255, BYW85, GP30K, 1N5407..08,++
1N2193	Si-Di	=1N2184: 1000V			BY255, BYW86, GP30M, 1N5408,++
1N2194	Si-Di	GI-L,50V,6A	32		BYX38/300, BYX39/600
1N2195	Si-Di	=1N2194: 100V	32		BYX38/300, BYX39/600
1N2196	Si-Di	=1N2194: 150V	32		BYX38/300, BYX39/600
1N2197	Si-Di	=1N2194: 200V	32		BYX38/300, BYX39/600
1N2198	Si-Di	=1N2194: 300V	32		BYX38/300, BYX39/600
1N2199	Si-Di	=1N2194: 400V	32		BYX38/600, BYX39/600
1N22	Si-Di	UHF,X-Band-Dem	Koax	Nec	—
1N220	Z-Di	=1N200: 330V	2c		—
1N2200	Si-Di	=1N2194: 500V	32		BYX38/600, BYX39/600
1N2201	Si-Di	=1N2194: 600V	32		BYX38/600, BYX39/600
1N2202	Si-Di	=1N2194: 600V	32		BYX38/900, BYX39/600
1N2203	Si-Di	=1N2194: 1000V	32		BYX38/1200, BYW38/1000
1N2204	Si-Di	GI-L,50V,12A	32		BYW88/50, BYX75..81, BYX99/300,++
1N2205	Si-Di	=1N2204: 100V	32		BYW88/100, BYX76..81, BYX99/300,++
1N2206	Si-Di	=1N2204: 150V	32		BYW88/200, BYX77..81, BYX99/300,++
1N2207	Si-Di	=1N2204: 200V	32		BYW88/200, BYX77..81, BYX99/300,++
1N2208	Si-Di	=1N2204: 300V	32		BYW88/300, BYX78..81, BYX99/300,++
1N2209	Si-Di	=1N2204: 400V	32		BYW88/400, BYX78..81, BYX, 99/600,++
1N221	Z-Di	=1N200: 390V	2c		—
1N2210	Si-Di	=1N2204: 500V	32		BYW88/500, BYX79..81, BYX99/800,++
1N2211	Si-Di	=1N2204: 600V	32		BYW88/600, BYX79..81, BYX99/600,++
1N2212	Si-Di	=1N2204: 800V	32		BYX88/800, BYX80..81, BYX99/900,++
1N2213	Si-Di	=1N2204: 1000V	32		BYX88/1000, BYX81, BYX99/1200,++
1N2214	Z-Di	5,5V,2%,1W	34a	USA	BZW22/C5V6, BZX61/C5V6, ZPY5,6, 1N5919,++
1N2216(A)	Si-Di	GI-L,50V,1,5A	32a	USA	BYX38/300, BYX39/600
1N2217(A)	Si-Di	=1N2216: Iso	32a		—
1N2218(A)	Si-Di	=1N2216: 500V	32a		BYX38/600, BYX39/600
1N2219(A)	Si-Di	=1N2216: 500V, Iso	32a		—
1N222	Z-Di	=1N200: 470V	2c		—
1N2220(A)	Si-Di	=1N2216: 800V	32a		BYX38/600, BYX39/800
1N2221(A)	Si-Di	=1N2216: 800V, Iso	32a		—
1N2222(A)	Si-Di	GI-L,800V,1A	32a	USA	BYX38/900, BYX39/600
1N2223(A)	Si-Di	=1N2222: Iso	32a		—
1N2224(A)	Si-Di	=1N2222: 1000V	32a		BYX38/1200, BYX39/1000
1N2225(A)	Si-Di	=1N2222: 1000V, Iso	32a		—
1N2226(A)	Si-Di	=1N2222: 1200V	32a		BYX38/1200, BYX38/1200

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1N2227(A)	Si-Di	=1N2222: 1200V, Iso	32a		—
1N2228(A)	Si-Di	GI-L, 50V, 5A	32a	USA	BYX 38/300, BYX 39/600
1N2229(A)	Si-Di	=1N2228: Iso	32a		—
1N2230(A)	Si-Di	=1N2228: 200V	32a		BYX 38/300, BYX 39/600
1N2231(A)	Si-Di	=1N2228: 200V, Iso	32a		—
1N2232(A)	Si-Di	=1N2228: 300V	32a		BYX 38/300+F2253, BYX 39/600
1N2233(A)	Si-Di	=1N2228: 300V, Iso	32a		—
1N2234(A)	Si-Di	=1N2228: 400V	32a		BYX 38/600, BYX 39/600
1N2235(A)	Si-Di	=1N2228: 400V, Iso	32a		—
1N2236(A)	Si-Di	=1N2228: 500V	32a		BYX 38/600, BYX 39/600
1N2237(A)	Si-Di	=1N2228: 500V, Iso	32a		—
1N2238(A)	Si-Di	=1N2228: 600V	32a		BYX 38/600, BYX 39/600
1N2239(A)	Si-Di	=1N2228: 600V, Iso	32a		—
1N2240(A)	Si-Di	=1N2228: 600V	32a		BYX 38/900, BYX 39/800
1N2241(A)	Si-Di	=1N2228: 600V, Iso	32a		—
1N2242(A)	Si-Di	=1N2228: 1000V	32a		BYX 38/1200, BYX 39/1000
1N2243(A)	Si-Di	=1N2228: 1000V, Iso	32a		—
1N2244(A)	Si-Di	=1N2228: 1200V	32a		BYX 38/1200, BYX 39/1200
1N2245(A)	Si-Di	=1N2228: 1200V, Iso	32a		—
1N2246(A)	Si-Di	GI-L, 50V, 10A	32a	USA	BYX 42/300, BYX 98/300
1N2247(A)	Si-Di	=1N2246: Iso	32a		—
1N2248(A)	Si-Di	=1N2248: 100V	32a		BYX 42/300, BYX, 98/300
1N2249(A)	Si-Di	=1N2246: 100V, Iso	32a		—
1N225	Z-Di	8,75V, 10%, 0,15W	2c	USA	BZX55/.., BZX79/.., ZPD.., 1N5238..74,++
1N2250(A)	Si-Di	=1N2246: 200V	32a		BYX 42/300, BYX, 98/300
1N2251(A)	Si-Di	=1N2246: 200V, Iso	32a		—
1N2252(A)	Si-Di	=1N2246: 300V	32a		BYX 42/300, BYX 98/300
1N2253(A)	Si-Di	=1N2248: 300V, Iso	32a		—
1N2254(A)	Si-Di	=1N2246: 400V	32a		BYX 42/600, BYX 98/600
1N2255(A)	Si-Di	=1N2246: 400V, Iso	32a		—
1N2256(A)	Si-Di	=1N2246: 500V	32a		BYX 42/600, BYX 98/600
1N2257(A)	Si-Di	=1N2246: 500V, Iso	32a		—
1N2258(A)	Si-Di	=1N2246: 600V	32a		BYX 42/600, BYX 98/600
1N2259(A)	Si-Di	=1N2246: 600V, Iso	32a		—
1N225A..235A	Z-Di	=1N225..235: 5%	2c		—
1N226	Z-Di	=1N225: 10,5V	2c		—
1N2260(A)	Si-Di	=1N2246: 800V	32a		BYX 42/900, BYX 98/900
1N2261(A)	Si-Di	=1N2246: 600V, Iso	32a		—
1N2262(A)	Si-Di	=1N2246: 1000V	32a		BYX 42/1200, BYX 98/1200
1N2263(A)	Si-Di	=1N2246: 1000V, Iso	32a		—
1N2264(A)	Si-Di	=1N2246: 1200V	32a		BYX 42/1200, BYX 98/1200
1N2265(A)	Si-Di	=1N2246: 1200V, Iso	32a		—
1N2266	Si-Di	GI-L, 50V, 1A	32a	USA	BYX 38/300, BYX 39/600
1N2267	Si-Di	=1N2266: Iso	32a		—
1N2268	Si-Di	=1N2268: 500V	32a		BYX 38/600, BYX 39/600
1N2269	Si-Di	=1N2266: 500V, Iso	32a		—
1N227	Z-Di	=1N225: 12,8V	2c		—
1N2270	Si-Di	=1N2268: 600V	32a		BYX 38/600, BYX 39/600
1N2271	Si-Di	=1N2266: 600V, Iso	32a		—
1N2272	Si-Di	GI-L, 50V, 6A(Tc=150°)	32a	USA	BYX 38/300, BYX 39/600
1N2273	Si-Di	=1N2272: 100V	32a		BYX 38/300, BYX 39/600
1N2274	Si-Di	=1N2272: 200V	32a		BYX 38/300, BYX 39/600
1N2275	Si-Di	=1N2272: 300V	32a		BYX 38/300, BYX 39/600
1N2276	Si-Di	=1N2272: 400V	32a		BYX 38/600, BYX 39/600
1N2277	Si-Di	=1N2272: 500V	32a		BYX 38/600, BYX 39/600
1N2278	Si-Di	=1N2272: 600V	32a		BYX 38/600, BYX 38/600
1N2279	Si-Di	=1N2272: 600V	32a		BYX 38/900, BYX 39/600
1N228	Z-Di	=1N225: 15,7V	2c		—
1N2280	Si-Di	=1N2272: 1000V	32a		BYX 38/1200, BYX 39/1000
1N2281	Si-Di	=1N2272: 1200V	32a		BYX 38/1200, BYX 39/1200
1N2282	Si-Di	GI-L, 300V, 20A(Tc=150°)	32a	USA	1N3765..68, 1N4525..30
1N2283	Si-Di	=1N2282: 400V	32a		1N3765..68, 1N4526..30
1N2284	Si-Di	=1N2282: 500V	32a		1N3765..68, 1N4527..30
1N2285	Si-Di	=1N2262: 600V	32a		1N3765..68, 1N4527..30
1N2286	Si-Di	=1N2262: 600V	32a		1N3768..68, 1N4528..30
1N2287	Si-Di	=1N2262: 1000V	32a		1N3768, 1N4529..30

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1N2288	Si-Di	=1N2282: 1200V	32a		1N4530
1N2289...2293	Si-Di	=1N2289A..2293A: Iso	32a		—
1N2289A	Si-Di	Gl-L, 100V, 1,5A	32a	USA	BYX38/300, BYX39/600
1N229	Z-Di	=1N225: 19V	2c		—
1N2290A	Si-Di	=1N2289A: 5A	32a		BYX38/300, BYX39/600
1N2291A	Si-Di	=1N2289A: 200V	32a		BYX38/300, BYX39/600
1N2292A	Si-Di	=1N2289A: 300V	32a		BYX38/300, BYX39/600
1N2293A	Si-Di	=1N2289A: 400V	32a		BYX38/600, BYX39/600
1N2294	Si-Di	Gl-L, 50V, 22A			BYX25/600, SSiE2040
1N2295	Si-Di	=1N2294: 100V			BYX25/600, SSiE2040
1N2296	Si-Di	=1N2294: 150V			BYX25/600, SSiE2040
1N2297	Si-Di	=1N2294: 200V			BYX25/600, SSiE2040
1N2298	Si-Di	=1N2294: 250V			BYX25/600, SSiE2040
1N2299	Si-Di	=1N2294: 300V			BYX25/600, SSiE2040
1N23	Si-Di	UHF, X-Band-M	Koax	Nec,Tho,++	—
1N230	Z-Di	=1N225: 23,5V	2c		—
1N2300	Si-Di	=1N2294:350V			BYX25/600, SSiE2040
1N2301	Si-Di	=1N2294: 400V			BYX25/600, SSiE2040
1N2302	Si-Di	Gl-L, 50V, 22A			BYX25/600, SSiE2040
1N2303	Si-Di	=1N2302: 100V			BYX25/600, SSiE2040
1N2304	Si-Di	=1N2302: 150V			BYX25/600, SSiE2040
1N2305	Si-Di	=1N2302: 200V			BYX25/600, SSiE2040
1N2306	Si-Di	=1N2302: 250V			BYX25/600, SSiE2040
1N2307	Si-Di	=1N2302: 300V			BYX25/600, SSiE2040
1N2308	Si-Di	=1N2302: 350V			BYX25/600, SSiE2040
1N2309	Si-Di	=1N2302: 400V			BYX25/600, SSiE2040
1N231	Z-Di	=1N225: 28,5V	2c		—
1N2310	Si-Di	Gl-L, 50V, 35A			1N3765..68, 1N4525..30
1N2311	Si-Di	=1N2310: 100V			1N3765..68, 1N4525..30
1N2312	Si-Di	=1N2310: 150V			1N3765..68, 1N4525..30
1N2313	Si-Di	=1N2310: 200V			1N3785..68, 1N4525..30
1N2314	Si-Di	=1N2310: 250V			1N3765..68, 1N4528..30
1N2315	Si-Di	=1N2310: 300V			1N3785..68, 1N4526..30
1N2316	Si-Di	=1N2310: 350V			1N3765..68, 1N4526..30
1N2317	Si-Di	=1N2310: 400V			1N3765..68, 1N4526..30
1N2318	Si-Di	Gl-L, 50V, 35A			1N3765..68, 1N4525..30
1N2319	Si-Di	=1N2318: 100V			1N3785..68, 1N4525..30
1N232	Z-Di	=1N225: 34,5V	2c		—
1N2320	Si-Di	=1N2318: 150V			1N3765..88, 1N4525..30
1N2321	Si-Di	=1N2318: 200V			1N3765..68, 1N4525..30
1N2322	Si-Di	=1N2318: 250V			1N3785..68, 1N4526..30
1N2323	Si-Di	=1N2318: 300V			1N3765..68, 1N4526..30
1N2324	Si-Di	=1N2318: 350V			1N3765..88, 1N4526..30
1N2325	Si-Di	=1N2318: 400V			1N3785..68, 1N4526..30
1N2326	Ge-Di	Stabi, 1V, 0,2A	2c	Rca	—
1N2327	Si-Di	Gl, 1100V, 0,4A	34a	Sam,Ssi	BY127, BY133, BYX94..95, GP10Q,++
1N2328	Si-Di	=1N2327: 2200V	34a		1N1732A, 1N1733A
1N233	Z-Di	=1N225: 41V	2c		—
1N234	Z-Di	=1N225: 48V	2c		—
1N2348	Si-Di	Gl-L, 50V, 3A(Tc=50°)	32a	Sem,Ssi	BYX38/300, BYX39/600
1N2349	Si-Di	=1N2348: 100V	32a		BYX38/300, BYX39/600
1N235	Z-Di	=1N225: 58V	2c		—
1N2350	Si-Di	=1N2348: 150V	32a		BYX38/300, BYX39/600
1N2357	Si-Di	Gl, 1400V, 0,4A	34a	USA	BY231/1400, BY268..289, GP10V,++
1N2358	Si-Di	=1N2357: 1500V	34a		BY231/1500, BY269, DM513, GP10W
1N2359	Si-Di	=1N2357: 1800V	34a		BY269, DM513, EM516, GP10Y
1N236	Z-Di	71V, 10%, 0,15W	2c		—
1N2360	Si-Di	=1N2357:1800V	34a		DM516, 1N1732A
1N2381	Si-Di	=1N2357: 2000V	34a		1N1732A
1N2362	Si-Di	Gl-L, 1400V, 1A	32a	USA	—
1N2362A...2371A	Si-Di	=1N2362..2371: 5A	32a		—
1N2362B..2371B	Si-Di	=1N2362..2371: 10A	32a		—
1N2363	Si-Di	=1N2362: Iso	32a		—
1N2364	Si-Di	=1N2362: 1500V	32a		—
1N2365	Si-Di	=1N2362: 1500V, Iso	32a		—
1N2366	Si-Di	=1N2362: 1600V	32a		—

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1N2367	Si-Di	=1N2362: 1600V, Iso	32a		—
1N2368	Si-Di	=1N2362: 1800V	32a		—
1N2369	Si-Di	=1N2362: 1800V, Iso	32a		—
1N237	Z-Di	=1N236: 68V	2c		—
1N2370	Si-Di	=1N2362: 2000V	32a		—
1N2371	Si-Di	=1N2362: 2000V, Iso	32a		—
1N2372	Si-Di	Gl-L, 1000V, 0,2A(Tc=150°)	32a	USA	—
1N2373	Si-Di	Gl, 600V, 0,25A	31a	USA	BY 126..127, BY 133..134, 1N4005..07,++
1N2374	Si-Di	Gl, 1000V, 0,25A	31a	USA	BY127, BY133, GP 10Q, 1N4007..07,++
1N2375	Si-Di	Gl, 1500V, 0,2A	31a	USA	BY231/1500, BY269, DM513, GP10W
1N2376	Si-Di	Gl, 2000V, 0,2A	31a	USA	HVG2, GP02-20, MR250-2, 1N1732(A)
1N2377	Si-Di	Gl, 2400V, 0,15A	31a	USA	HVG3, GP02-30, MR250-3, 1N1733(A)
1N2378	Si-Di	Gl, 3000V, 0,15A	31a	USA	HVG3, GP02-30, MR250-3, 1N1733(A)
1N2379	Si-Di	Gl, 4000V, 0,15A	31a	USA	HVG4, GP02-40, MR250-4, 1N1734(A)
1N236	Z-Di	=1N236: 105V	2c		—
1N2380	Si-Di	Gl, 8000V, 0,1A	31a	USA	BYX90, 1N5183
1N2361	Si-Di	Gl, 10kV, 0,075A	31a	USA	1N3052
1N2362	Si-Di	kV-Gl, 4kV, 0,15A	31a	Gen,Mot,++	HVG4, GP02-40, MR250-4, 1N1734(A)
1N2382A	Si-Di	=1N2362 0,35A	31a		1N1734A
1N2383	Si-Di	kV-Gl, 6kV, 0,1A	31a	Gen,Mot,++	BYX90, 1N5183
1N2363A	Si-Di	=1N2363: 0,35A	31a		—
1N2384	Si-Di	kV-Gl, 6kV, 0,07A	31a	Gen,Mot,++	1N5164
1N2364A	Si-Di	=1N2364: 0,275A	31a		—
1N2385	Si-Di	kV-Gl, 10kV, 0,07A	31a	Gen,Mot,++	1N5184
1N2385A	Si-Di	=1N2364: 0,2A	31a		—
1N2386	Ge-Di	UHF, 5V	Koax	old	—
1N2367	Z-Di	30V, 10%, 1W	34a	Sem,Ssi	BZW22/C10, BZX81/C10, ZPY10, 1N5925,++
1N2389	Si-Di	Dual, Gl, 1600V, 0,6A		USA	—
1N239	Z-Di	=1N236: 126V	2c		—
1N2390(A)	Si-Di	Gl, 50V, 1,5A		USA	BY228..227, BY251..255, 1N5391..99,++
1N2391(A)	Si-Di	=1N2390: 100V			BY226..227, BY251..255, 1N5392..99,++
1N2392(A)	Si-Di	=1N2390: 200V			BY226..227, BY251..255, 1N5393..99,++
1N2393(A)	Si-Di	=1N2390: 300V			BY226..227, BY252..255, 1N5394..99,++
1N2394(A)	Si-Di	=1N2390: 400V			BY226..227, BY252..255, 1N5395..99,++
1N2395(A)	Si-Di	=1N2390: 500V			BY226..227, BY253..255, 1N5396..99,++
1N2396(A)	Si-Di	=1N2390: 600V			BY226..227, BY253..255, 1N5397..99,++
1N2397(A)	Si-Di	=1N2390: 700V			BY227, BY254..255, 1N5398..99,++
1N2396(A)	Si-Di	=1N2390: 800V			BY227, BY254..255, 1N5398..99,++
1N2399(A)	Si-Di	=1N2390			→1N2390
1N2400(A)	Si-Di	=1N2391			→1N2391
1N2401(A)	Si-Di	=1N2392			→1N2392
1N2402(A)	Si-Di	=1N2393			→1N2393
1N2403(A)	Si-Di	=1N2394			→1N2394
1N2404(A)	Si-Di	=1N2395			→1N2395
1N2405(A)	Si-Di	=1N2398			→1N2398
1N2406(A)	Si-Di	=1N2397			→1N2397
1N2407(A)	Si-Di	=1N2396			→1N2398
1N2406(A)	Si-Di	=1N2390			→1N2390
1N2409(A)	Si-Di	=1N2391			→1N2391
1N2410(A)	Si-Di	=1N2392			→1N2392
1N2411(A)	Si-Di	=1N2393			→1N2393
1N2412(A)	Si-Di	=1N2394			→1N2394
1N2413(A)	Si-Di	=1N2395			→1N2395
1N2414(A)	Si-Di	=1N2398			→1N2398
1N2415(A)	Si-Di	=1N2397			→1N2397
1N2416(A)	Si-Di	=1N2398			→1N2398
1N2417(A)	Si-Di	=1N2390			→1N2390
1N2416(A)	Si-Di	=1N2391			→1N2391
1N2418(A)	Si-Di	=1N2392			→1N2392
1N2420(A)	Si-Di	=1N2393			→1N2393
1N2421(A)	Si-Di	=1N2394			→1N2394
1N2422(A)	Si-Di	=1N2395			→1N2395
1N2423(A)	Si-Di	=1N2398			→1N2396
1N2424(A)	Si-Di	=1N2397			→1N2397
1N2425(A)	Si-Di	=1N2398			→1N2398
1N2426	Si-Di	Gl-L, 50V, 100A(Tc=75°)	73a	USA	1N3268..97

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1N2427	Si-Di	=1N2326:100V	73a		1N3288..97
1N2428	Si-Di	=1N2326:150V	73a		1N3289..97
1N2429	Si-Di	=1N2328:200V	73a		1N3289..97
1N2430	Si-Di	=1N2326:250V	73a		1N3290..97
1N2431	Si-Di	=1N2326:300V	73a		1N3290..97
1N2432	Si-Di	=1N2326:350V	73a		1N3291..97
1N2433	Si-Di	=1N2328:400V	73a		1N3291..97
1N2434	Si-Di	=1N2328:500V	73a		1N3292..97
1N2435	Si-Di	=1N2328:600V	73a		1N3293..97
1N2436	Si-Di	Gl-L, 50V, 150A(Tc=75°)	73a	USA	1N4587..96
1N2437	Si-Di	=1N2436:100V	73a		1N4587..96
1N2436	Si-Di	=1N2436:150V	73a		1N4588..96
1N2439	Si-Di	=1N2436:200V	73a		1N4588..96
1N2440	Si-Di	=1N2436:250V	73a		1N4589..96
1N2441	Si-Di	=1N2436:300V	73a		1N4589..96
1N2442	Si-Di	=1N2436:350V	73a		1N4590..96
1N2443	Si-Di	=1N2436:400V	73a		1N4590..96
1N2444	Si-Di	=1N2436:500V	73a		1N4591..96
1N2445	Si-Di	=1N2436:600V	73a		1N4592..96
1N2446	Si-Di	Gl-L, 50V, 45A(Tc=60°)	32a	USA	—
1N2447	Si-Di	=1N2446:100V	32a		—
1N2446	Si-Di	=1N2446:150V	32a		—
1N2449	Si-Di	=1N2446:200V	32a		—
1N2450	Si-Di	=1N2446:250V	32a		—
1N2451	Si-Di	=1N2446:300V	32a		—
1N2452	Si-Di	=1N2446:350V	32a		—
1N2453	Si-Di	=1N2446:400V	32a		—
1N2454	Si-Di	=1N2446:500V	32a		—
1N2455	Si-Di	=1N2446:600V	32a		—
1N2458	Si-Di	=1N2446:700V	32a		—
1N2457	Si-Di	=1N2446:800V	32a		—
1N2458	Si-Di	Gl-L, 50V, 60A(Tc=60°)	32a	USA	—
1N2458	Si-Di	=1N2458:100V	32a		—
1N2460	Si-Di	=1N2458:150V	32a		—
1N2461	Si-Di	=1N2458:200V	32a		—
1N2462	Si-Di	=1N2458:250V	32a		—
1N2463	Si-Di	=1N2458:300V	32a		—
1N2464	Si-Di	=1N2458:350V	32a		—
1N2465	Si-Di	=1N2458:400V	32a		—
1N2488	Si-Di	=1N2458:500V	32a		—
1N2467	Si-Di	=1N2458:600V	32a		—
1N2488	Si-Di	=1N2458:700V	32a		—
1N2469	Si-Di	=1N2458:600V	32a		—
1N248(A...C)	Si-Di	Gl-L, 50..55V, 10..20A	32a	Mot, Rca,++	BYX25/600
1N248(A...C)R	Si-Di	=1N246(A..C):	32b		BYX25/600R, DS 17-02A, SSiE2040
1N2462	Si-Di	Gl, 200V, 0,75A	31a	USA	BY128..127, BY133..134, 1N4003..07, ++
1N2463	Si-Di	=1N2482:400V	31a		BY128..127, BY133..134, 1N4004..07, ++
1N2484	Si-Di	=1N2482:600V	31a		BY128..127, BY133..134, 1N4005..07, ++
1N2485	Si-Di	Gl, 200V, 0,75A	34a	USA	BY128..127, BY133..134, 1N4003..07, ++
1N2486	Si-Di	=1N2465:300V	34a		BY128..127, BY133..134, 1N4004..07, ++
1N2487	Si-Di	=1N2485:400V	34a		BY128..127, BY133..134, 1N4004..07, ++
1N2486	Si-Di	=1N2465:500V	34a		BY128..127, BY133..134, 1N4005..07, ++
1N2489	Si-Di	=1N2485:600V	34a		BY128..127, BY133..134, 1N4005..07, ++
1N249(A...C)	Si-Di	Gl-L, 100..110V, 10..20A	32a	Mot, Rca,++	BYX25/600
1N249(A...C)R	Si-Di	=1N249(A..C):	32b		BYX25/600R, DS 17-02A, SSiE2040
1N2490	Si-Di	Dual, Gl, 1600V, 0,5A		USA	—
1N2491	Si-Di	Gl-L, 50V, 6A(Tc=150°)	32a	USA	BYX38/300, BYX39/600
1N2492	Si-Di	=1N2491:100V	32a		BYX38/300, BYX39/600
1N2493	Si-Di	=1N2491:200V	32a		BYX38/300, BYX39/600
1N2494	Si-Di	=1N2491:300V	32a		BYX38/300, BYX39/600
1N2495	Si-Di	=1N2491:400V	32a		BYX38/600, BYX39/600
1N2496	Si-Di	=1N2491:500V	32a		BYX38/600, BYX39/600
1N2497	Si-Di	=1N2491:600V	32a		BYX38/600, BYX39/600
1N2496	Z-Di	10V, 10%, 10W	32	USA, Mot, Sie	BZX98/.., BZY93/.., 1N2974..76
1N2498A..2500A	Z-Di	=1N2498..2500: 5%	32		—
1N2498C..2500C	Z-Di	=1N2496..2500: bidirektional	32		—

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1N2499	Z-Di	=1N2498: 11V	32		—
1N25	Si-Di	UHF, L-Band-M	Koax	USA	—
1N250(A..C)	Si-Di	GI-L, 200..220V, 10..20A	32a	Mot, Rca, ++	BYX 25/600
1N250(A..C)R	Si-Di	=1N250(A..C)	32b		BYX 25/600R, DS 17-02A, SSiE2040
1N2500	Z-Di	=1N2498: 12V	32		—
1N2501	Si-Di	GI, 800V, 0,15A	34a	USA	BA 159, BAY 90, BY 203/12, SHG 1
1N2502	Si-Di	=1N2501: 1000V	34a		BA 159, BAY 90, BY 203/12, SHG 1
1N2503	Si-Di	=1N2501: 1200V	34a		BAY 91, BY 203/12, SHG 1,5
1N2504	Si-Di	=1N2501: 1500V	34a		BAY 91, BY 203/15, SHG 1,5
1N2505	Si-Di	GI, 800V, 0,3A	34a	USA	BA 159, BAY 90, BY 203/12, GP 10Q, ++
1N2506	Si-Di	=1N2505: 1000V	34a		BA 159, BAY 90, BY 203/12, GP 10Q, ++
1N2507	Si-Di	=1N2505: 1200V	34a		BAY 91, BY 203/12, EM 513, GP 10Q, ++
1N2506	Si-Di	=1N2505: 1500V	34a		BAY 91, BY 203/15, EM 516, GP 10Y, ++
1N2509	Si-Di	UHF, C-Band-M	Koax	USA	—
1N251	Si-Di	S, 40V, 75mA, <150ns	31a	Sgs, Tix, ++	BAY 16..21, BAX 15..17, 1N3070, ++
1N2510	Si-Di	UHF, X-Band-M	Koax	USA	—
1N2512	Si-Di	GI-L, 100V, 4A(Tc=30°)	32a	USA	BYX 38/300, BYX 39/600
1N2512R..2523R	Si-Di	=1N2512..2523:	32b		BYX38/..R, BYX39/..R
1N2513	Si-Di	=1N2512: 200V	32a		BYX 38/300, BYX 39/800
1N2514	Si-Di	=1N2512: 300V	32a		BYX 38/300, BYX 39/600
1N2515	Si-Di	=1N2512: 400V	32a		BYX 38/600, BYX 39/600
1N2516	Si-Di	=1N2512: 500V	32a		BYX 38/600, BYX 39/600
1N2517	Si-Di	=1N2512: 600V	32a		BYX 38/600, BYX 39/600
1N2516	Si-Di	=1N2512: Iso	32a		—
1N2519	Si-Di	=1N2513: Iso	32a		—
1N251A	Si-Di	=1N251: 125V, 100mA	31a		BAV 19..21, BAX 15..17, 1N3070, ++
1N252	Si-Di	S, 20V, 100mA, <150ns	31a	Sgs, Tix, ++	BAV 16..21, BAX 15..17, 1N3070, ++
1N2520	Si-Di	=1N2514: Iso	32a		—
1N2521	Si-Di	=1N2515: Iso	32a		—
1N2522	Si-Di	=1N2516: Iso	32a		—
1N2523	Si-Di	=1N2517: Iso	32a		—
1N2524	Si-Di	GI-L, 50V, 2,5A(Tc=150°)	32a	USA	—
1N2525	Si-Di	=1N2524: 100V	32a		—
1N2526	Si-Di	=1N2524: 200V	32a		—
1N2527	Si-Di	=1N2524: 300V	32a		—
1N2526	Si-Di	=1N2524: 400V	32a		—
1N2529	Si-Di	=1N2524; 500V	32a		—
1N252A	Si-Di	=1N252: 125V	313		BAV 19..21, BAX 15..17, 1N3070, ++
1N253	Si-Di	GI-L, 95V, 1A	32a	Ssi, Tix, ++	BYX 38/300, BYX 39/600
1N2530	Si-Di	=1N2524: 600V	32a		—
1N2531	Si-Di	=1N2524: 700V	32a		—
1N2532	Si-Di	=1N2524: 600V	32a		—
1N2533	Si-Di	=1N2524: 900V	32a		—
1N2534	Si-Di	=1N2524: 1000V	32a		—
1N2535	Si-Di	GI-L, 50V, 2,5A(Tc=150°)	32a	USA	—
1N2536	Si-Di	=1N2535: 100V	32a		—
1N2537	Si-Di	=1N2535: 200V	32a		—
1N2538	Si-Di	=1N2535: 300V	32a		—
1N2539	Si-Di	=1N2535: 400V	32a		—
1N254	Si-Di	=1N253: 190V, 0,4A	32a	SSi, Tix, ++	BYX 38/300, BYX 39/600
1N2540	Si-Di	=1N2535: 500V	32a		—
1N2541	Si-Di	=1N2535: 600V	32a		—
1N2542	Si-Di	=1N2535: 700V	32a		—
1N2543	Si-Di	=1N2535: 800V	32a		—
1N2544	Si-Di	=1N2535: 900V	32a		—
1N2545	Si-Di	=1N2535: 1000V	32a		—
1N2546	Si-Di	GI-L, 50V, 2,5A(Tc=150°)	32a	USA	—
1N2547	Si-Di	=1N2546: 100V	32a		—
1N2546	Si-Di	=1N2546: 200V	32a		—
1N2549	Si-Di	=1N2546: 300V	32a		—
1N255	Si-Di	=1N253: 380V, 0,4A	32a	SSi, Tix, ++	BYX 38/600, BYX 39/600
1N2550	Si-Di	=1N2546: 400V	32a		—
1N2551	Si-Di	=1N2546: 500V	32a		—
1N2552	Si-Di	=1N2546: 800V	32a		—
1N2553	Si-Di	=1N2546: 700V	32a		—
1N2554	Si-Di	=1N2546: 800V	32a		—

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1N2555	Si-Di	=1N2546: 900V	32a		—
1N2556	Si-Di	=1N2546: 1000V	32a		—
1N2557	Si-Di	Gl-L, 700V, 6A(Tc=150°)	32a	U6A	—
1N2558	Si-Di	=1N2557: 800V	32a		—
1N2559	Si-Di	=1N2557: 900V	32a		—
1N256	Si-Di	=1N253: 570V, 0,2A	32a	SSi, Tix, ++	BYX 38/600, BYX 39/600
1N2560	Si-Di	=1N2557: 1000V	32a		—
1N2561	Si-Di	Gl-L, 700V, 6A(Tc=150°)	32a	USA	—
1N2562	Si-Di	=1N2561: 600V	32a		—
1N2563	Si-Di	=1N2561: 900V	32a		—
1N2564	Si-Di	=1N2561: 1000V	32a		—
1N2565	Si-Di	Gl-L, 50V, 6A(Tc=150°)	32a	USA	—
1N2566	Si-Di	=1N2565: 100V	32a		—
1N2567	Si-Di	=1N2565: 200V	32a		—
1N2568	Si-Di	=1N2565: 300V	32a		—
1N2569	Si-Di	=1N2565: 400V	32a		—
1N2570	Si-Di	=1N2565: 500V	32a		—
1N2571	Si-Di	=1N2565: 600V	32a		—
1N2572	Si-Di	=1N2565: 700V	32a		—
1N2573	Si-Di	=1N2565: 800V	32a		—
1N2574	Si-Di	=1N2565: 900V	32a		—
1N2575	Si-Di	=1N2565: 1000V	32a		—
1N2576	Si-Di	Gl-L, 50V, 12A(Tc=150°)	32a	USA	—
1N2577	Si-Di	=1N2576: 100V	32a		—
1N2578	Si-Di	=1N2576: 200V	32a		—
1N2579	Si-Di	=1N2576: 300V	32a		—
1N258	Si-Di	UHF, S-Band-Dem	Koax	U6A	—
1N2560	Si-Di	=1N2576: 400V	32a		—
1N2581	Si-Di	=1N2576: 500V	32a		—
1N2562	Si-Di	=1N2576. 800V	32a		—
1N2563	Si-Di	=1N2576: 700V	32a		—
1N2564	Si-Di	=1N2576: 600V	32a		—
1N2565	Si-Di	=1N2576: 900V	32a		—
1N2586	Si-Di	=1N2576: 1000V	32a		—
1N2587	Si-Di	Gl-L, 50V, 12A(Tc=150°)	32a	USA	—
1N2568	Si-Di	=1N2587: 100V	32a		—
1N2569	Si-Di	=1N2587: 200V	32a		—
1N259	Si-Di	=2x1N23gep			—
1N2590	Si-Di	=1N2587: 300V	32a		—
1N2591	Si-Di	=1N2587: 400V	32a		—
1N2592	Si-Di	=1N2587: 500V	32a		—
1N2593	Si-Di	=1N2587: 600V	32a		—
1N2594	Si-Di	=1N2587: 700V	32a		—
1N2595	Si-Di	=1N2587: 600V	32a		—
1N2596	Si-Di	=1N2567 900V	32a		—
1N2597	Si-Di	=1N2567: 1000V	32a		—
1N2598	Si-Di	Gl-L, 50V, 12A(Tc=150°)	32a	USA	—
1N2599	Si-Di	=1N2598: 100V	32a		—
1N26	Si-Di	UHF, K-Band-M	Koax	USA	—
1N2600	Si-Di	=1N2598: 200V	32a		—
1N2601	Si-Di	=1N2598: 300V	32a		—
1N2602	Si-Di	=1N2598: 400V	32a		—
1N2603	Si-Di	=1N2598: 500V	32a		—
1N2604	Si-Di	=1N2598: 600V	32a		—
1N2605	Si-Di	=1N2598: 700V	32a		—
1N2606	Si-Di	=1N2598: 600V	32a		—
1N2607	Si-Di	=1N2598: 600V	32a		—
1N2608	Si-Di	=1N2598: 1000V	32a		—
1N2609	Si-Di	Gl, 50V, 0,75A	34a	USA, Mot	BY126..127, BY133..135, 1N4001..07, ++
1N261	Di	400V			—
1N2610	Si-Di	=1N2609: 100V	34a		BY126..127, BY133..135, 1N4002..07, ++
1N2611	Si-Di	=1N2609: 200V	34a		BY126..127, BY133..134, 1N4003..07, ++
1N2612	Si-Di	=1N2609: 300V	34a		BY126..127, BY133..134, 1N4004..07, ++
1N2613	Si-Di	=1N2609: 400V	34a		BY126..127, BY133..134, 1N4004..07, ++
1N2614	Si-Di	=1N2609: 500V	34a		BY126..127, BY133..134, 1N4005..07, ++
1N2615	Si-Di	=1N2609: 600V	34a		BY126..127, BY133..134, 1N4005..07, ++

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1N2616	Si-Di	=1N2609: 800V	34a		BY127, BY133, EM513, 1N4006..07, ++
1N2617	Si-Di	=1N2609: 1000V	34a		BY127, BY133, EM513, 1N4007, ++
1N2618	Si-Di	=1N2609: 1200V	34a		BY127, BY133, EM513, GP10Q, ++
1N2619	Si-Di	=1N2609: 1500V	34a		BY400, BY448, DM513, EM516, GP10W
1N2620(A,B)	Ref-Di	9,3V, 5%, 0,75W	34a	USA, Mot, Sie	—
1N2621(A,B)	Ref-Di	9,3V, 5%, 0,75W	34a		—
1N2622(A,B)	Ref-Di	9,3V, 5%, 0,75W	34a		—
1N2623(A,B)	Ref-Di	9,3V, 5%, 0,75W	34a		—
1N2624(A,B)	Ref-Di	9,3V, 5%, 0,75W	34a		—
1N2625(A,B)	Ref-Di	9,3V, 5%, 0,75W	34a		—
1N2626(A,B)	Ref-Di	9,3V, 5%, 0,75W	34a		—
1N2627	Ge-Di	UHF-Tuning, 5V	Koax	old	—
1N2628	Ge-Di	UHF-Tuning, 5V	Koax	old	—
1N2629	Ge-Di	UHF, 5V	Koax	old	—
1N263	Ge-Di	UHF-M	Koax	Miv, Nec, Pai	—
1N2630	Si-Di	Dual, kV-Gl, 1500V, 0,085A		USA	—
1N2631	Si-Di	Dual, kV-Gl, 1800V, 0,6A		USA	—
1N2632	Si-Di	Dual, kV-Gl, 2800V, 0,2A		USA	—
1N2633	Si-Di	Dual, kV-Gl, 1800V, 0,6A		USA	—
1N2634	Si-Di	Dual, kV-Gl, 1800V, 0,6A		USA	—
1N2635	Si-Di	Dual, kV-Gl, 1500V, 0,085A		USA	—
1N2636	Si-Di	Dual, kV-Gl, 1500V, 0,085A		USA	—
1N2637	Si-Di	Dual, kV-Gl, 10kV, 0,25A		USA	—
1N2638	Si-Di	Gl-Stack, 100V, 1,5A		USA	—
1N264	Si-Di	=2x1N21 gep			—
1N2641	Si-Di	=1N2638: 200V			—
1N2644(A)	Si-Di	=1N2638: 300V			—
1N2647(A)	Si-Di	=1N2638: 400V			—
1N285	Ge-Di	Uni, 60V	31a	USA	AA117..116, AA132..133
1N2650(A)	Si-Di	=1N2638: 800V			—
1N2653(A)	Si-Di	=1N2638: 800V			—
1N2656	Si-Di	=1N2638: 1200V			—
1N2659	Si-Di	=1N2638: 1800V			—
1N266	Ge-Di	Uni, 50V	31a	USA	AA117..116, AA132..134, 1N34, 1N54, ++
1N2662	Si-Di	=1N2638: 2000V			—
1N2664	Si-Di	=1N2638: 2400V			—
1N2666	Si-Di	=1N2638: 3200V			—
1N2667	Si-Di	=1N2638: 4000V			—
1N2668	Si-Di	=1N2638: 4800V			—
1N2669	Si-Di	Gl-Stack, 100V, 3,6A		USA	—
1N267	Ge-Di	Uni, 30V	31a	USA	AA117..118, AA132..134, 1N34, 1N54, ++
1N2673	Si-Di	=1N2669: 200V			—
1N2677	Si-Di	=1N2669: 300V			—
1N266	Ge-Di	Uni, 30V, 300mA	31a	USA	AA139, 1N270
1N2661	Si-Di	=1N2669: 400V			—
1N2685	Si-Di	=1N2669: 800V			—
1N2687	Si-Di	=1N2669: 800V			—
1N2889	Si-Di	=1N2669: 900V			—
1N2690	Si-Di	=1N2669: 1200V			—
1N2691	Si-Di	=1N2669: 1800V			—
1N2692	Si-Di	Gl-Stack, 100V, 7,2A		USA	—
1N2694	Si-Di	=1N2692: 200V			—
1N2696	Si-Di	=1N2692: 300V			—
1N2696	Si-Di	=1N2892: 400V			—
1N270	Ge-Di	Uni, 100V, 60mA	31a	USA, Ift, Tho	AA117..118, AA132..133
1N2700	Si-Di	=1N2892: 800V			—
1N2701	Si-Di	=1N2692: 800V			—
1N2702	Si-Di	Gl-Stack, 100V, 3A		USA	—
1N2705	Si-Di	=1N2702: 200V			—
1N2708	Si-Di	=1N2702: 300V			—
1N2711	Si-Di	=1N2702: 400V			—
1N2714	Si-Di	=1N2702: 600V			—
1N2717	Si-Di	=1N2702: 800V			—
1N2720	Si-Di	=1N2702: 1200V			—
1N2722	Si-Di	=1N2702: 1800V			—
1N2723	Si-Di	=1N2702: 2000V			—

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1N2724	Si-Di	=1N2702: 2400V			—
1N2725	Si-Br	Gl-Stack, 100V, 3A		USA	—
1N2728	Si-Br	=1N2725: 200V			—
1N273	Ge-Di	Uni, 32V, 80mA	31a	USA	AA117..118, AA132..133, 1N34, 1N54, ++
1N2731	Si-Br	=1N2725: 300V			—
1N2734	Si-Br	=1N2725: 400V			—
1N2737	Si-Br	=1N2725: 600V			—
1N2738	Si-Br	=1N2725: 600V			—
1N2739	Si-Br	=1N2725: 1200V			—
1N2740	Si-Br	Gl-Stack, 100V, 3,6A		USA	—
1N2742	Si-Br	=1N2740: 200V			—
1N2744	Si-Br	=1N2740: 300V			—
1N2746	Si-Br	=1N2740: 400V			—
1N2748	Si-Br	=1N2740: 600V			—
1N2749	Si-Br	=1N2740: 600V			—
1N2750	Si-Br	Gl-Stack, 100V, 3A		USA	—
1N2753	Si-Br	=1N2750: 200V			—
1N2756	Si-Br	=1N2750: 300V			—
1N2759	Si-Br	=1N2750: 400V			—
1N276	Ge-Di	Uni, S, 100V, 60mA, <300ns	31a	USA,Itt,Tho	AAY28, AAZ15
1N2762	Si-Br	=1N2750: 600V			—
1N2763	Si-Br	=1N2750: 600V			—
1N2764	Si-Br	=1N2750: 1200V			—
1N2765(A)	Ref-Di	6,8V, 5%	31a	USA	—
1N2766(A)	Ref-Di	=1N2765: 13,6V	31a		—
1N2767(A)	Ref-Di	=1N2765: 20,4V	31a		—
1N2768(A)	Ref-Di	=1N2765: 27,2V	31a		—
1N2769(A)	Ref-Di	=1N2765: 34V	31a		—
1N277(M)	Ge-Di	Uni, 100..125V, 50mA	31a	USA	AA117..118, AA132..133
1N2770(A)	Ref-Di	=1N2765: 40,8V	31a		—
1N2771	Si-Di	UHF, PQ=1W(750MHz)	Koax	USA	—
1N2772	Si-Di	Gl, 700V, 0,75A	34a	USA	BY127, BY133, EM513, 1N4006..07, ++
1N2773	Si-Di	=1N2772: 600V	34a		BY127, BY133, EM513, 1N4006..07, ++
1N2774	Si-Di	=1N2772: 900V	34a		BY127, BY133, EM513, 1N4007, ++
1N2775	Si-Di	=1N2772: 1000V	34a		BY127, BY133, EM513, 1N4007, ++
1N2776	Si-Di	=1N2772: 1100V	34a		BY127, BY133, EM513, GP10Q, ++
1N2777	Si-Di	=1N2772: 1200V	34a		BY127, BY133, EM513, GP10Q, ++
1N2778	Si-Di	=1N2772: 1300V	34a		BY400, BY448, EM513, GP10V, ++
1N2779	Si-Di	=1N2772: 1400V	34a		BY400, BY448, EM516, GP10V, ++
1N278	Ge-Di	Uni, 56V, 0,17A(ss)	31a	USA,Itt	AA117..118, AA132..134, 1N34, 1N54, ++
1N2760	Si-Di	=1N2772: 1500V	34a		BY400, BY448, EM516, GP10Y, ++
1N2761	Si-Di	=1N2772: 1600V	34a		BY400, BY448, EM516, GP10Y, ++
1N2782	Di	UHF-Dem		Alp	—
1N2783	Z-Di	62V, 10%, 6W			—
1N2784	Si-Di	Gl-L, 200V, 22A(Tc=40°)	32a	USA	BYX96/300
1N2785	Si-Di	=1N2784: 400V	32a		BYX96/600
1N2786	Si-Di	Gl-L, 200V, 10A	32a	USA	BYW88/200, BYX77..81
1N2787	Si-Di	=1N2786: 400V	32a		BYW88/400, BYX78..81
1N2788	Si-Di	Gl-L, 200V, 50A(Tc=40°)	32a	USA	—
1N2789	Si-Di	=1N2788: 400V	32a		—
1N279	Ge-Di	Uni, 32V, 70mA	31a	USA,Itt	AA117..118, AA132..134, 1N34, 1N54, ++
1N2790	Ref-Di	8,5V, 5%, 1W	34a	Ssi	BZX53, 1N4762
1N2791	Si-Di	Gl, S, 350V	31	Ssi	BA157..159, BA199/350, BAY21, ++
1N2792(A,B)	Ge-Di	UHF-M, 70GHz		Phc	—
1N2793	Si-Di	Gl-L, 50V, 8,5A	32a	USA	BYW88/50, BYX75..81
1N2794	Si-Di	=1N2793: 100V	32a		BYW88/100, BYX76..81
1N2795	Si-Di	=1N2793: 150V	32a		BYW88/200, BYX77..81
1N2796	Si-Di	=1N2793: 200V	32a		BYW88/200, BYX77..81
1N2797	Si-Di	=1N2793: 250V	32a		BYW88/300, BYX78..81
1N2798	Si-Di	=1N2793: 300V	32a		BYW88/300, BYX78..81
1N2799	Si-Di	=1N2793: 350V	32a		BYW88/400, BYX78..81
1N28	Si-Di	UHF, S-Band-Dem	Koax	Nec	—
1N2800	Si-Di	=1N2793: 400V	32a		BYW88/400, BYX78..81
1N2801	Ge-Di	Gl, S, 20V, <500ns	32a	USA	—
1N2802	Si-Di	UHF, X-Band-M		USA	—
1N2803	Si-Di	Gl, 400V, 250A			—

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1N2804	Z-Di	6,6V, 20%, 50W(Tc=75°)	23n	Mot,Sie,Tho	—
1N2804A..2846A	Z-Di	=1N2804..2846: 10%	23n		—
1N2804B..2846B	Z-Di	=1N2804..2846: 5%	23n		—
1N2804R..2846R	Z-Di	=1N2804..2846:	23f		—
1N2805	Z-Di	=1N2804: 7,5V	23n		—
1N2806	Z-Di	=1N2804: 6,2V	23n		—
1N2807	Z-Di	=1N2804: 9,1V	23n		—
1N2806	Z-Di	=1N2804: 10V	23n		—
1N2809	Z-Di	=1N2804: 11V	23n		—
1N281	Ge-Di	Uni, 75V, 75mA	31a	USA,Tho	AA117..116, AA132..134, 1N34, 1N54, ++
1N2810	Z-Di	=1N2804: 12V	23n		—
1N2811	Z-Di	=1N2604: 13V	23n		—
1N2812	Z-Di	=1N2804: 14V	23n		—
1N2813	Z-Di	=1N2804: 15V	23n		—
1N2814	Z-Di	=1N2804: 16V	23n		—
1N2815	Z-Di	=1N2804: 17V	23n		—
1N2816	Z-Di	=1N2804: 18V	23n		—
1N2817	Z-Di	=1N2804: 19V	23n		—
1N2818	Z-Di	=1N2804: 20V	23n		—
1N2819	Z-Di	=1N2804: 22V	23n		—
1N282	Ge-Di	Uni, 15V	31a	USA	AA113..119, 1N34, 1N54, 1N60, ++
1N2820	Z-Di	=1N2804: 24V	23n		—
1N2821	Z-Di	=1N2804: 25V	23n		—
1N2822	Z-Di	=1N2804: 27V	23n		—
1N2823	Z-Di	=1N2804: 30V	23n		—
1N2824	Z-Di	=1N2804: 33V	23n		—
1N2825	Z-Di	=1N2804: 36V	23n		—
1N2828	Z-Di	=1N2804: 39V	23n		—
1N2827	Z-Di	=1N2804: 43V	23n		—
1N2828	Z-Di	=1N2804: 45V	23n		—
1N2829	Z-Di	=1N2804: 47V	23n		—
1N283	Ge-Di	Uni, 25V	31a	USA,Itt,Tho	AA139
1N2830	Z-Di	=1N2804: 50V	23n		—
1N2831	Z-Di	=1N2804: 51V	23n		—
1N2832	Z-Di	=1N2804: 56V	23n		—
1N2833	Z-Di	=1N2804: 82V	23n		—
1N2834	Z-Di	=1N2804: 68V	23n		—
1N2835	Z-Di	=1N2804: 75V	23n		—
1N2836	Z-Di	=1N2804: 82V	23n		—
1N2837	Z-Di	=1N2804: 91V	23n		—
1N2836	Z-Di	=1N2804: 100V	23n		—
1N2839	Z-Di	=1N2804: 105V	23n		—
1N2840	Z-Di	=1N2804: 110V	23n		—
1N2841	Z-Di	=1N2804: 120V	23n		—
1N2842	Z-Di	=1N2804: 130V	23n		—
1N2843	Z-Di	=1N2804: 150V	23n		—
1N2844	Z-Di	=1N2804: 180V	23n		—
1N2845	Z-Di	=1N2804: 180V	23n		—
1N2846	Z-Di	=1N2804: 200V	23n		—
1N2847(A)	Si-Di	Gl-L, 100V, 1,5A(T=75°)	32a	USA	—
1N2848(A)	Si-Di	=1N2847: 200V	32a		—
1N2849(A)	Si-Di	=1N2847: 300V	32a		—
1N285	Ge-Di	UHF-M		Gen	—
1N2850(A)	Si-Di	=1N2847: 400V	32a		—
1N2851(A)	Si-Di	=1N2847: 500V	32a		—
1N2852(A)	Si-Di	=1N2847: 600V	32a		—
1N2855	Si-Di	Gl-L, 600V, 250A			—
1N2856	Si-Di	=1N2855: 600V			—
1N2857	Si-Di	=1N2855: 1000V			—
1N2858(A)	Si-Di	Gl, 50V, 0,75..1A	34a	USA,Rca	BY128..127, BY133..135, 1N4001..07, ++
1N2859(A)	Si-Di	=1N2858: 100V	34a		BY128..127, BY133..135, 1N4002..07, ++
1N286(A)	Si-Di	UHF, X/K-Band-M	Koax	Syl	—
1N2860(A)	Si-Di	=1N2858: 200V	34a		BY128..127, BY133..134, 1N4003..07, ++
1N2861(A)	Si-Di	=1N2858: 300V	34a		BY128..127, BY133..134, 1N4004..07, ++
1N2862(A)	Si-Di	=1N2858: 400V	34a		BY128..127, BY133..134, 1N4004..07, ++
1N2863(A)	Si-Di	=1N2858: 500V	34a		BY128..127, BY133..134, 1N4005..07, ++

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1N2864(A)	Si-Di	=1N2858: 600V	34a		BY 128..127, BY 133..134, 1N4005..07, ++
1N2865	Si-Di	Gl, 1000V, 0,7A	34a	Scn, Sem	BY 127, BY 133, GP 10Q, 1N4007, ++
1N2866	Si-Di	=1N2865: 1500V	34a		BY 400, BY 448, EM 516, GP 10W, ++
1N2867	Si-Di	Gl, 1000V, 0,7A		Scn, Sem	BY 127, BY 133, GP 10Q, 1N4007, ++
1N2868	Si-Di	=1N2867: 1500V			BY 400, BY 448, EM 516, GP 10W, ++
1N287	Ge-Di	Uni, 40V, 60mA	31a	USA	AA 117..118, AA 132..134, 1N34, 1N54, ++
1N2878	Si-Di	Gl, 700V, 0,25A	33a	USA, Tho	BA 158..159, BAY 90, BY 203/12, ++
1N2879	Si-Di	=1N2878: 1000V	31a		BA 159, BAY 90, BY 203/12, SHG 1, ++
1N288	Ge-Di	Uni, 70V, 0,75A(ss)	31a	USA	AA 117..118, AA 132..134, 1N34, 1N54, ++
1N2880	Si-Di	=1N2878: 1000V	31a		BA 159, BAY 90, BY 203/12, SHG 1, ++
1N2881	Si-Di	=1N2878: 1000V	31a		BA 159, BAY 90, BY 203/12, SHG 1, ++
1N2882	Si-Di	=1N2878: 1000V	31a		BA 159, BAY 90, BY 203/12, SHG 1, ++
1N2883	Si-Di	=1N2878: 1000V	31a		BA 159, BAY 90, BY 203/12, SHG 1, ++
1N2884	Si-Di	=1N2878: 1400V	31a		BAY 91, BY 203/16, GP 10W, SHG 1,5, ++
1N2885	Si-Di	=1N2878: 1400V	31a		BAY 91, BY 203/18, GP 10W, SHG 1,5, ++
1N2886	Si-Di	=1N2878: 1500V	31a		BAY 91, BY 203/16, GP 10W, SHG 1,5, ++
1N2887	Si-Di	=1N2878: 1500V	31a		BAY 91, BY 203/18, GP 10W, SHG 1,5, ++
1N2888	Si-Di	=1N2878: 1700V	31a		BAY 91, BY 203/20, DM 516, SHG 2, ++
1N2889	Si-Di	=1N2878: 1700V	31a		BAY 91, BY 203/20, DM 516, SHG 2, ++
1N289	Ge-Di	Uni, 60V, 80mA	31a	USA	AA 117..118, AA 132..134, 1N34, 1N54, ++
1N2890	Si-Di	=1N2878: 2000V	31a		BAY 91, BY 203/20, SHG 2, 1N1732(A)
1N2891	Si-Di	=1N2878: 2000V	31a		BAY 91, BY 203/20, SHG 2, 1N1732(A)
1N2892	Si-Di	=1N2878: 2100V	31a		GP 02-30, MR 250-3, SHG 2,5, 1N1733(A)
1N2893	Si-Di	=1N2878: 2100V	31a		GP 02-30, MR 250-3, SHG 2,5, 1N1733(A)
1N2894	Si-Di	=1N2878: 2400V	31a		GP 02-30, MR 250-3, SHG 2,5, 1N1733(A)
1N2895	Si-Di	=1N2878: 2400V	31a		GP 02-30, MR 250-3, SHG 2,5, 1N1733(A)
1N2896	Si-Di	=1N2878: 2500V	31a		GP 02-30, MR 250-3, SHG 2,5, 1N1733(A)
1N2897	Si-Di	=1N2878: 2500V	31a		GP 02-30, MR 250-3, SHG 2,5, 1N1733(A)
1N2898	Si-Di	=1N2878: 2800V	31a		GP 02-30, MR 250-3, SHG 2,5, 1N1733(A)
1N2899	Si-Di	=1N2878: 2800V	31a		GP 02-30, MR 250-3, SHG 2,5, 1N1733(A)
1N290	Ge-Di	Uni, 100V, 0,3A(ss)	31a	USA	AA 117..118, AA 132..133
1N2900	Si-Di	=1N2878: 3000V	31a		GP 02-30, MR 250-3, SHG 2,5, 1N1733(A)
1N2901	Si-Di	=1N2878: 3000V	31a		GP 02-30, MR 250-3, SHG 2,5, 1N1733(A)
1N2902	Si-Di	=1N2878: 3100V	31a		GP 02-40, HVG 4, MR 250-4, 1N1734(A)
1N2903	Si-Di	=1N2878: 3100V	31a		GP 02-40, HVG 4, MR 250-4, 1N1734(A)
1N2904	Si-Di	=1N2878: 3500V	31a		GP 02-40, HVG 4, MR 250-4, 1N1734(A)
1N2905	Si-Di	=1N2878: 3500V	31a		GP 02-40, HVG 4, MR 250-4, 1N1734(A)
1N2906	Si-Di	=1N2878: 3500V	31a		GP 02-40, HVG 4, MR 250-4, 1N1734(A)
1N2907	Si-Di	=1N2878: 3500V	31a		GP 02-40, HVG 4, MR 250-4, 1N1734(A)
1N2908	Si-Di	=1N2878: 3800V	31a		GP 02-40, HVG 4, MR 250-4, 1N1734(A)
1N2909	Si-Di	=1N2878: 3800V	31a		GP 02-40, HVG 4, MR 250-4, 1N1733(A)
1N291	Ge-Di	Uni, 100V, 0,4A(ss)	31a	USA	AA 117..118, AA 132..133
1N2910	Si-Di	=1N2878: 4000V	31a		GP 02-40, HVG 4, MR 250-4, 1N1734(A)
1N2911	Si-Di	=1N2878: 4000V	31a		GP 02-40, HVG 4, MR 250-4, 1N1734(A)
1N2912	Si-Di	=1N2878: 4200V	31a		HVG 5, MR 250-5, 1N1734(A)
1N2913	Si-Di	=1N2878: 4200V	31a		HVG 5, MR 250-5, 1N1734(A)
1N2914	Si-Di	=1N2878: 4500V	31a		HVG 5, MR 250-5, 1N1734(A)
1N2915	Si-Di	=1N2878: 4500V	31a		HVG 5, MR 250-5, 1N1734(A)
1N2916	Si-Di	=1N2878: 4500V	31a		HVG 5, MR 250-5, 1N1734(A)
1N2917	Si-Di	=1N2878: 4500V	31a		HVG 5, MR 250-5, 1N1734(A)
1N2918	Si-Di	=1N2878: 5000V	31a		HVG 5, MR 250-5, 1N1734(A)
1N2919	Si-Di	=1N2878: 5000V	31a		HVG 5, MR 250-5, 1N1734(A)
1N292	Ge-Di	Uni, 70V, 70mA	31a	USA	AA 117..118, AA 132..134, 1N34, 1N54, ++
1N2920	Si-Di	=1N2878: 5500V	31a		BYX 90
1N2921	Si-Di	=1N2878: 5500V	31a		BYX 90
1N2922	Si-Di	=1N2878: 6000V	31a		BYX 90
1N2923	Si-Di	=1N2878: 6000V	31a		BYX 90
1N2924	Si-Di	=1N2378: 8500V	31a		BYX 90
1N2925	Si-Di	=1N2378: 8500V	31a		BYX 90
1N2926(A)	Si-Di	UHF, K/X-Band-Dem	Koax	Pai, Syl	—
1N2927(A)	Si-Di	Tunnel-Di	31	Msc	—
1N2928(A)	Si-Di	Tunnel-Di	31	Msc	—
1N2929(A)	Si-Di	Tunnel-Di	31	Msc	—
1N2930(A)	Si-Di	Tunnel-Di	31	Msc	—
1N2931(A)	Si-Di	Tunnel-Di	31	Msc	—
1N2932(A)	Si-Di	Tunnel-Di	31	Msc	—

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1N2933(A)	Si-Di	Tunnel-Di	31	Msc	—
1N2934(A)	Si-Di	Tunnel-Di	31	Msc	—
1N2937	Z-Di	50V, 15%, 10W	32	USA	BZX98/C51, BZY93/C51, 1N2998
1N2938	Z-Di	0,9V, 15%	32	USA	—
1N2939(A)	Ge-Di	Tunnel-Di	31	Gen	—
1N294(A)	Ge-Di	Uni, 60V, 50mA	31a	USA, Tho	AA117..118, AA132..134, 1N34, 1N54, ++
1N2940(A)	Ge-Di	Tunnel-Di	31	Gen	—
1N2941(A)	Ge-Di	Tunnel-Di	31	Gen	—
1N2942	Z-Di	8,2V, 5%, 50W		Scn	—
1N2943	Z-Di	=1N2942: 9,1V			—
1N2944	Z-Di	=1N2942: 10V			—
1N2945	Z-Di	=1N2942: 11V			—
1N2946	Z-Di	=1N2942: 12V			—
1N2947	Z-Di	=1N2942: 13V			—
1N2948	Z-Di	=1N2942: 15V			—
1N2949	Z-Di	=1N2942: 16V			—
1N295(A,S,X)	Ge-Di	Uni, 30..40V, 20..35mA	31a	USA, Tho	AA117..118, AA132..134, 1N34, 1N54, ++
1N2950	Z-Di	=1N2942: 18V			—
1N2951	Z-Di	=1N2942:20V			—
1N2952	Z-Di	=1N2942:22V			—
1N2953	Z-Di	=1N2942:24V			—
1N2954	Z-Di	=1N2942:27V			—
1N2955	Z-Di	=1N2942:30V			—
1N2956	Z-Di	=1N2942:33V			—
1N2957	Z-Di	=1N2942:36V			—
1N2958	Z-Di	=1N2942:39V			—
1N2959	Z-Di	=1N2942:43V			—
1N296	Ge-Di	40V			—
1N2960	Z-Di	=1N2942:47V			—
1N2961	Z-Di	=1N2942:51V			—
1N2962	Z-Di	=1N2942:56V			—
1N2963	Z-Di	=1N2942:62V			—
1N2964	Z-Di	=1N2942:68V			—
1N2965	Z-Di	=1N2942:75V			—
1N2966	Z-Di	=1N2942:82V			—
1N2967	Z-Di	=1N2942:91V			—
1N2968	Z-Di	=1N2942:100V			—
1N2969(A)	Ge-Di	Tunnel-Di	31	Gen	—
1N297(A)	Ge-Di	Uni, 60V, 35mA	31a	USA, Tho	AA117..118, AA132..134, 1N34, 1N54, ++
1N2970	Z-Di	6,8V, 20%, 10W(Tc=55°)	32b	USA, Sie, Tho	BZX98/.., BZY93/.., ZL.., ZX..F2909
1N2970A...3015A	Z-Di	=1N2970..3015: 10%	32b		—
1N2970B...3015B	Z-Di	=1N2970..3015: 5%	32b		—
1N2970R...3015R	Z-Di	=1N2970..3015	32a		—
1N2971	Z-Di	=1N2970: 7,5V	32b		—
1N2972	Z-Di	=1N2970:8,2V	32b		—
1N2973	Z-Di	=1N2970:9,1V	32b		—
1N2974	Z-Di	=1N2970:10V	32b		—
1N2975	Z-Di	=1N2970:11V	32b		—
1N2976	Z-Di	=1N2970:12V	32b		—
1N2977	Z-Di	=1N2970:13V	32b		—
1N2978	Z-Di	=1N2970:14V	32b		—
1N2979	Z-Di	=1N2970:15V	32b		—
1N298(A)	Ge-Di	Uni, 70V, 30..50mA	31a	USA	AA117..118, AA132..134, 1N34, 1N54, ++
1N2980	Z-Di	=1N2970:16V	32b		—
1N2981	Z-Di	=1N2970:17V	32b		—
1N2982	Z-Di	=1N2970:18V	32b		—
1N2983	Z-Di	=1N2970:19V	32b		—
1N2984	Z-Di	=1N2970:20V	32b		—
1N2985	Z-Di	=1N2970:22V	32b		—
1N2986	Z-Di	=1N2970:24V	32b		—
1N2987	Z-Di	=1N2970:25V	32b		—
1N2988	Z-Di	=1N2970:27V	32b		—
1N2989	Z-Di	=1N2970:30V	32b		—
1N299	Ge-Di	Uni, 50V	31a	Kem	AA117..118, AA132..134, 1N34, 1N54, ++
1N2990	Z-Di	=1N2970:33V	32b		—
1N2991	Z-Di	=1N2970:36V	32b		—

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1N2992	Z-Di	=1N2970:39V	32b		—
1N2993	Z-Di	=1N2970:43V	32b		—
1N2994	Z-Di	=1N2970:45V	32b		—
1N2995	Z-Di	=1N2970:47V	32b		—
1N2996	Z-Di	=1N2970:50V	32b		—
1N2997	Z-Di	=1N2970:51V	32b		—
1N2996	Z-Di	=1N2970:52V	32b		—
1N2999	Z-Di	=1N2970:56V	32b		—
1N300(A,B)	Si-Di	Uni, 15V, 65..100mA	31a	USA	BA127, BA147/25, 1N4148, 1N5194..96, ++
1N3000	Z-Di	=1N2970:62V	32b		—
1N3001	Z-Di	=1N2970:68V	32b		—
1N3002	Z-Di	=1N2970:75V	32b		—
1N3003	Z-Di	=1N2970:82V	32b		—
1N3004	Z-Di	=1N2970:91V	32b		—
1N3005	Z-Di	=1N2970:100V	32b		—
1N3006	Z-Di	=1N2970:105V	32b		—
1N3007	Z-Di	=1N2970:110V	32b		—
1N3008	Z-Di	=1N2970:120V	32b		—
1N3009	Z-Di	=1N2970:130V	32b		—
1N301(A,B)	Si-Di	Uni, 70V, 45..75mA		USA	BA127, BA147/100, 1N4148, 1N5194..96, ++
1N3010	Z-Di	=1N2970:140V	32b		—
1N3011	Z-Di	=1N2970:150V	32b		—
1N3012	Z-Di	=1N2970:160V	32b		—
1N3013	Z-Di	=1N2970:175V	32b		—
1N3014	Z-Di	=1N2970:180V	32b		—
1N3015	Z-Di	=1N2970:200V	32b		—
1N3016	Z-Di	6,6V, 20%, 1W	34a	USA, Sie, Tho	BZW22/.., BZX61/.., ZPY.., 1N5921..56++
1N3016A..3051A	Z-Di	=1N3016..3051: 10%	34a		—
1N3016B..3051B	Z-Di	=1N3016..3051: 5%	34a		—
1N3017	Z-Di	=1N3016: 7,5V	34a		—
1N3016	Z-Di	=1N3016: 8,2V	34a		—
1N3019	Z-Di	=1N3016: 9,1V	34a		—
1N302(A,B)	Si-Di	Uni, 225V, 30..55mA		USA	BA147/230, BAY21, BAY46, 1N5196, ++
1N3020	Z-Di	=1N3016: 10V	34a		—
1N3021	Z-Di	=1N3016: 11V	34a		—
1N3022	Z-Di	=1N3016: 12V	34a		—
1N3023	Z-Di	=1N3016: 13V	34a		—
1N3024	Z-Di	=1N3016: 15V	34a		—
1N3025	Z-Di	=1N3016: 16V	34a		—
1N3026	Z-Di	=1N3016: 16V	34a		—
1N3027	Z-Di	=1N3016: 20V	34a		—
1N3026	Z-Di	=1N3016: 22V	34a		—
1N3029	Z-Di	=1N3016: 24V	34a		—
1N303(A,B)	Si-Di	Uni, 125V, 40..65mA	31a	USA	BA147/150, BAY20, BAY45, 1N5195..96++
1N3030	Z-Di	=1N3016: 27V	34a		—
1N3031	Z-Di	=1N3016: 30V	34a		—
1N3032	Z-Di	=1N3016: 33V	34a		—
1N3033	Z-Di	=1N3016: 36V	34a		—
1N3034	Z-Di	=1N3016: 39V	34a		—
1N3035	Z-Di	=1N3016: 43V	34a		—
1N3036	Z-Di	=1N3016: 47V	34a		—
1N3037	Z-Di	=1N3016: 51V	34a		—
1N3036	Z-Di	=1N3016: 56V	34a		—
1N3039	Z-Di	=1N3018: 62V	34a		—
1N304	Ge-Di	Uni, 55V	31a	USA	AA117..118, AA132..134, 1N34, 1N54, ++
1N3040	Z-Di	=1N3016: 68V	34a		—
1N3041	Z-Di	=1N3016: 75V	34a		—
1N3042	Z-Di	=1N3016: 62V	34a		—
1N3043	Z-Di	=1N3016: 91V	34a		—
1N3044	Z-Di	=1N3016: 100V	34a		—
1N3045	Z-Di	=1N3018: 110V	34a		—
1N3046	Z-Di	=1N3016: 120V	34a		—
1N3047	Z-Di	=1N3016: 130V	34a		—
1N3048	Z-Di	=1N3016: 150V	34a		—
1N3049	Z-Di	=1N3016: 180V	34a		—
1N305	Ge-Di	Uni, 80V, 125mA	31a	USA	AA136, 1N270

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1N3050	Z-Di	=1N3016: 180V	34a		—
1N3051	Z-Di	=1N3016: 200V	34a		—
1N3052	Si-Di	kV-Gl, 12kV, 0,1A	31a	USA	—
1N3053	Si-Di	=1N3052: 14kV	31a		—
1N3054	Si-Di	=1N3052: 16kV	31a		—
1N3055	Si-Di	=1N3052: 18kV	31a		—
1N3056	Si-Di	=1N3052: 20kV	31a		—
1N3057	Si-Di	=1N3052: 22kV	31a		—
1N3058	Si-Di	=1N3052: 24kV	31a		—
1N3059	Si-Di	=1N3052: 26kV	31a		—
1N306	Ge-Di	Uni, 15V, 150mA	31a	USA	AA135..136, AA139, 1N270
1N3060	Si-Di	=1N3052: 28kV	31a		—
1N3061	Si-Di	=1N3052: 30kV	31a		—
1N3062	Si-Di	SS, 50V, 0,075A, <4ns	31a	USA, Tho	BA218, BAX13, BAX91, 1N4148..49, ++
1N3063	Si-Di	SS, 50V, 0,075A, <4ns	31a		BA218, BAX13, BAX91, 1N4148..49, ++
1N3064	Si-Di	SS, 50V, 0,075A, <4ns	31a		BA218, SAX13, BAX91, 1N4148..49, ++
1N3065	Si-Di	SS, 50V, 0115A, <4ns	31a	USA, Tho	BA218, BAX13, BAX91, 1N4148..49, ++
1N3066	Si-Di	SS, 50V, 0,115A, <2ns	31a		BA218, BAX13, BAX91, 1N4148..49, ++
1N3067	Si-Di	SS, 30V, 0,115A, <4ns	31a		BA218, BAX13, BAX91, 1N4148..49, ++
1N3066	Si-Di	S, 30V, 0,075A, <50ns	31a	Fch, Tix, ++	BAV17..21, BAX90, BAX94, BAY41, ++
1N3069	Si-Di	S, 65V, 0,225A, <50ns	31a	USA, Tho	BAV18..21, BAW48..50, BAY72, ++
1N307	Ge-Di	Uni, 125V, 50mA		USA	AA117..118, AA132..133
1N3070	Si-Di	Uni, S, 200V, 0,15A, <50ns	31a	USA, Tho	BA197..198, BAV20..21, BAW50, ++
1N3071	Si-Di	S, 200V, 0,225A, <50ns	31a	Fch, Tix, ++	BA197..198, BAV20..21, BAW50, ++
1N3072	Si-Di	Gl, 50V, 0,2A(Tc=150°)	34a	USA	BY126..127, BY133..135, 1N4001..07, ++
1N3073	Si-Di	=1N3072: 100V	34a		BY126..127, BY133..135, 1N4002..07, ++
1N3074	Si-Di	=1N3072: 150V	34a		BY126..127, BY133..135, 1N4003..07, ++
1N3075	Si-Di	=1N3072: 200V	34a		BY126..127, BY133..134, 1N4003..07, ++
1N3076	Si-Di	=1N3072: 250V	34a		BY126..127, BY133..134, 1N4004..07, ++
1N3077	Si-Di	=1N3072: 300V	34a		BY126..127, BY133..134, 1N4004..07, ++
1N3078	Si-Di	=1N3072: 350V	34a		BY126..127, BY133..134, 1N4004..07, ++
1N3079	Si-Di	=1N3072: 400V	34a		BY126..127, BY133..134, 1N4004..07, ++
1N306	Ge-Di	Uni, 8V, 100mA	31a	USA	AA139
1N3080	Si-Di	=1N3072: 500V	34a		BY126..127, BY133..134, 1N4005..07, ++
1N3061	Si-Di	=1N3072: 600V	34a		BY126..127, BY133..134, 1N4005..07, ++
1N3062	Si-Di	Gl, 200V, 0,5A	34a	USA	BY126..127, BY133..134, 1N4003..07, ++
1N3063	Si-Di	=1N3082: 400V	34a		BY126..127, BY133..134, 1N4004..07, ++
1N3084	Si-Di	=1N3082: 600V	34a		BY126..127, BY133..134, 1N4005..07, ++
1N3065	Si-Di	Gl, 100V, 150A(Tc=150°)	73a	Inr, Sem, Ssi	1N4587..96
1N3066	Si-Di	=1N3085: 200V	73a		1N4588..96
1N3087	Si-Di	=1N3085: 300V	73a		1N4589..96
1N3066	Si-Di	=1N3065: 400V	73a		1N4590..96
1N3069	Si-Di	=1N3065: 500V	73a		1N4591..96
1N309	Ge-Di	Uni, 30V, 100mA	31a	USA	AA135..136, AA139, 1N270
1N3090	Si-Di	=1N3085: 600V	73a		1N4592..96
1N3091	Si-Di	=1N3065: 800V	73a		1N4593..96
1N3092	Si-Di	=1N3085: 1000V	73a		1N4594..96
1N3093	Ge-Di	UHF, X-Band-S			—
1N3097	Ge-Di	Uni, S, 30V, 0,05A, <500ns	31a	Idc, Sem	AAY49, AAZ15, AAZ17, 1N276
1N3098	Z-Di	120V, 20%, 1W	34a	Sem, Ssi	BZW22/.., BZX61/.., ZPY.., 1N5951..56, ++
1N3098A...3101A	Z-Di	=1N3098..3101: 10%	34a		—
1N3099	Z-Di	=1N3096: 145V	34a		—
1N31(A)	Si-Di	UHF, X-Band-Dem	Koax	USA	—
1N310	Ge-Di	Uni, 100V, 40mA	31a	USA	AA117..118, AA132..133
1N3100	Z-Di	=1N3096: 180V	34a		—
1N3101	Z-Di	=1N3096: 220V	34a		—
1N3102	Z-Di	120V, 10%, 10W	32	Scn	BZX98/.., BZY93/.., ZX.., 1N3008..15
1N3102A...3105A	Z-Di	=1N3102..3105: 5%	32		—
1N3103	Z-Di	=1N3102: 150V	32		—
1N3104	Z-Di	=1N3102: 180V	32		—
1N3105	Z-Di	=1N3102: 220V	32		—
1N3106	Si-Di	Gl, 600V, 0,75A	34a	Scn, Sem	BY127, BY133, BYX94..95, 1N4006..07 ++
1N3107	Si-Di	=1N3106: 1200V, 0,5A	34a		BY127, BY133, BYX94..95, GP10Q, ++
1N3106	Si-Di	Gl, 800V, 1,5A	32	Scn, Sem	BY227, BY254..255, 1N5062, 1N5398, ++
1N3109	Si-Di	=1N3108: 1200V, 0,7A	32		BY227, BY255, BY350/1300, GH3E, ++
1N311	Si-Di	UHF-M, 8,5GHz			—

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1N3110	Ge-Di	S, 12V, 0,05A	31a	USA	AAY27, AAZ18, 1N3592
1N3111	Si-Di	Gl, 50V, 150A(Tc=150°)	73a	Inr,Ssi	1N4587..96
1N3112	Z-Di	7,4V,5%, 1W	34a	Sem	BZW22/C7V5, BZX61/C7V5, ZPY7,5, 1N5922, ++
1N3113	GaAs-Di	Tunnel-Di	34a	Gen	—
1N3114	GaAs-Di	Tunnel-Di	34a	Gen	—
1N3115	GaAs-Di	Tunnel-Di	34a	Gen	—
1N3116	GaAs-Di	Tunnel-Di	34a	Gen	—
1N3117	GaAs-Di	Tunnel-Di	34a	Gen	—
1N3118	GaAs-Di	Tunnel-Di	34a	Gen	—
1N3119	GaAs-Di	Tunnel-Di	34a	Gen	—
1N312	Ge-Di	Uni, 50V, 70mA	31a	USA	AA117..118, AA132..134, 1N34, 1N54, ++
1N3120	GaAs-Di	Tunnel-Di	34a	Gen	—
1N3121	Ge-Di	Uni, S, 50V, 0,11A, <500ns	31a	USA	AAZ15, AAZ17
1N3122	Ge-Di	S, 20V, 0,18A, <3500ns	31a	USA	AA139, AAZ18
1N3123	Si-Di	SS, 40V, 0,05A, <4ns	31a	USA	BA218, BAX13, BAX91, 1N4148..49, ++
1N3124	Si-Di	SS, 40V, 0,05A, <4ns	31a		BA218, BAX13, BAX91, 1N4148..49, ++
1N3125	Ge-Di	S, 55V, 300ns	31a	USA	AAY28, 1N631, 1N633
1N3128	Ge-Di	Tunnel-Di		Kmc,Rca	—
1N3129	Ge-Di	Tunnel-Di		Kmc,Rca	—
1N313	Ge-Di	Uni, 100V, 40mA	31a	USA	AA117..118, AA132..133
1N3130	Ge-Di	Tunnel-Di		Kmc,Rca	—
1N3138	GaAs-Di	Tunnel-Di		Kmc,Rca	—
1N3139	Si-Di	Gl-L+C3018, 50V, 70A(Tc=150°)	32	Edl,Sem	—
1N314	Ge-Di	Uni, 75V, 100mA	31a	USA	1N270
1N3140	Si-Di	=1N3139: 100V	32		—
1N3141	Si-Di	=1N3139: 150V	32		—
1N3142	Si-Di	=1N3139: 200V	32		—
1N3143	Si-Di	UHF, C/X-Band-Dem	Koax	USA	—
1N3144	Ge-Di	S, 20V, 500ns			AAY49, AAZ15, AAZ17, 1N276
1N3145	Ge-Di	Uni, 65V			AA117..118, AA132..134
1N3146	Ge-Di	SS, 25V, <2ns	31a	USA	—
1N3147	Si-Di	Uni, 60V	31a	Sem	BA127, BA187..190, BAY19..21, ++
1N3148	Ref-Di	8,5V, 0,4W	34a	Idc,8	1N4779, 1N4784
1N3149(A)	Ge-Di	Tunnel-Di		Gen	—
1N315(A)	Ge-Di	Gl, 200..300V, 75..100mA	34a	Gen,Spe,Ssi	—
1N3150	Ge-Di	Tunnel-Di		Gen	—
1N3151	Si-Di	kV-Gl, 7,2kV, 0,1A	31a	Sem	BYX90, 1N5183
1N3152	Si-Di	UHF, 38GHz		Wes	—
1N3153	Si-Di	UHF, 38GHz		Wes	—
1N3154(A)	Ref-Di	8,4V, 5%, 0,4W	31a	USA,Sie,Tho	BZX51, 1N4775, 1N4780
1N3155(A)	Ref-Di	8,4V, 5%, 0,4W	31a		BZX52, 1N4776, 1N4781
1N3156(A)	Ref-Di	8,4V, 5%, 0,4W	31a		BZX53, 1N4777, 1N4781
1N3157(A)	Ref-Di	8,4V, 5%, 0,4W	31a		BZX54, 1N4778, 1N4783
1N3159	Ge-Di	S, 15V, 0,08A, <300ns	31a	USA	AAY27..28, AAZ18, 1N631, 1N633
1N316(A)	Si-Di	Gl, 50V, 0,25A	34a	USA	BA157..159, BAY18..21, BAY86..90, ++
1N3160	Ge-Di	Uni, 60V, 0,03A	31a	Sem	AAY27..28, AAZ18, 1N631, 1N633
1N3161	Si-Di	Gl-L, 50V, 175A(Tc=150°)	73a	USA	1N3735..44
1N3161R..3177R	Si-Di	=1N3161..3177:	73b		1N3735R...3744R
1N3162	Si-Di	=1N3161: 100V	73a		1N3735..44
1N3163	Si-Di	=1N3161: 150V	73a		1N3738..44
1N3164	Si-Di	=1N3161: 200V	73a		1N3736..44
1N3165	Si-Di	=1N3161: 250V	73a		1N3737..44
1N3166	Si-Di	=1N3161: 300V	73a		1N3737..44
1N3167	Si-Di	=1N3161: 350V	73a		1N3738..44
1N3168	Si-Di	=1N3161: 400V	73a		1N3738..44
1N3169	Si-Di	=1N3161: 500V	73a		1N3739..44
1N317(A)	Si-Di	=1N316: 100V	34a	USA	BA157..159, BAY19..21, BAY87..90, ++
1N3170	Si-Di	=1N3161: 600V	73a		1N3740..44
1N3171(A)	Si-Di	=1N3161: 700V, 240A	73a		1N3741..44
1N3172(A)	Si-Di	=1N3161: 800V, 240A	73a		1N3741..44
1N3173(A)	Si-Di	=1N3161: 900V, 240A	73a		1N3742..44
1N3174(A)	Si-Di	=1N3161: 1000V, 240A	73a		1N3742..44
1N3175(A)	Si-Di	=1N3161: 1200V, 240A	73a		1N3743..44
1N3176(A)	Si-Di	=1N3161: 1200V, 240A	73a		1N3744+F3059
1N3177(A)	Si-Di	=1N3161: 1600V, 240A	73a		—
1N3179	Si-Di	Gl, Uni, 240V	31a	Sem,Trw	BY126..127, BY133..134, 1N4004..07, ++

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1N318(A)	Si-Di	=1N316: 200V	34a	USA	BA157..159, BAY21, BAY88..90, ++
1N3180	Si-Di	Gl, Uni, 130V	31a	Sem, Trw	BY126..127, BY133..135, 1N4003..07, ++
1N3181	Z-Di	bidirektional, 7,7V, 10%, 0,6W	33	Idc, Sty	—
1N3182	Si-Di	VHF-Tuning	31a	USA	—
1N3183	Si-Br	Gl, 350V, 0,5A		Scn	B350C500
1N3184	Si-Br	=1N3183: 500V			B500C500
1N3185	Si-Br	=1N3183: 700V			B700C500
1N3186	Si-Br	=1N3183: 1000V			B1000C500
1N3187	Si-Br	=1N3183: 1500V			B1500C500
1N3188	Si-Br	=1N3183: 2000V			B2000C500
1N3189	Si-Di	Gl, 200V, 1A	34a	USA, Mot, Tho	BY226..227, BY251..255, 1N5393..99, ++
1N319(A)	Si-Di	=1N316: 350V	34a	USA	BA157..159, BAY21, BAY88..90, ++
1N3190	Si-Di	=1N3189: 400V	34a		BY226..227, BY252..255, 1N5395..99, ++
1N3191	Si-Di	=1N3189: 600V	34a		BY226..227, BY253..255, 1N5397..99, ++
1N3192	Si-Di	200V		Wes	—
1N3193	Si-Di	Gl, 200V, 0,75A	34a	USA, Rca, Tos	BY126..127, BY133..134, 1N4003..07, ++
1N3194	Si-Di	=1N3193: 400V	34a		BY126..127, BY133..134, 1N4004..07, ++
1N3195	Si-Di	=1N3193: 600V	34a		BY126..127, BY133..134, 1N4005..07, ++
1N3196	Si-Di	=1N3193: 800V	34a		BY127, BY133, BY227, 1N4006..07, ++
1N3197	Ge-Di	S, 30V, 0,08A, <300ns	31a	USA	AAY49, AAZ15, AAZ17
1N3198	Z-Di	2,25V, 2%, 0,4W	31a	Idc, Sem	—
1N3199	Ref-Di	8,4V, 5%, 0,27W	31a	Idc, Sem	BZX52, 1N4778, 1N4781
1N32(A)	Si-Di	UHF, S-Band-Dem	Koax	USA	—
1N320(A)	Si-Di	=1N318: 500V	34a	USA	BA158..159, BAY89..90
1N3200	Ref-Di	8,4V, 5%, 0,27W	31a		BZX53, 1N4777, 1N4782
1N3201	Ref-Di	8,4V, 5%, 0,27W	31a		BZX53, 1N4777, 1N4782
1N3202	Ref-Di	8,4V, 5%, 0,27W	31a		BZX54, 1N4778, 1N4783
1N3203	Ge-Di	S, 25V, 0,08A, 300ns	31a	USA	AAY49, AAZ15, AAZ17, 1N278
1N3204	Ge-Di	S, 80V, 0,08A, 300ns	31a	UBA	AAY28, AAZ15, AAZ17, 1N276
1N3205	Si-Di	UHF, Ku-Band-M	Koax	USA	—
1N3206	Si-Di	Min, SS, 100V, 0,075A, <4ns	31a	USA	(BA219, BAX96)
1N3207	Si-Di	Min, SS, 80V, <8ns	31a	USA	(BAW62, BAX95, 1N4148..49, 1N4151, ++)
1N3208	Si-Di	Gl-L, 50V, 15A(Tc=150°)	32a	USA, Mot	1N4525..30
1N3208R...3214R	Si-Di	=1N3208..3214:	32b		D24C/..
1N3209	Si-Di	=1N3208: 100V	32a		1N4525..30
1N321(A)	Si-Di	=1N316: 850V	34a	USA	BA159, BAY90..91
1N3210	Si-Di	=1N3208: 200V	32a		1N4525..30
1N3211	Si-Di	=1N3208: 300V	32a		1N4526..30
1N3212	Si-Di	=1N3208: 400V	32a		1N4526..30
1N3213	Si-Di	=1N3208: 500V	32a		1N4527..30
1N3214	Si-Di	=1N3208: 600V	32a		1N4527..30
1N3215	Si-Di	S, 80V, <250ns	31a		SAW21, BAX15..17, 1N4148..49, ++
1N3217	Ge-Di	Tunnel-Di		Gen	—
1N3218(A)	Ge-Di	Tunnel-Di		Gen	—
1N3219(A)	Ge-Di	Tunnel-Di		Gen	—
1N322(A)	Si-Di	=1N318: 1000V	34a	USA	BA159, BAY90..91
1N3220	Ge-Di	Tunnel-Di		Gen	—
1N3221(A)	Ge-Di	Tunnel-Di		Gen	—
1N3222	Ge-Di	Tunnel-Di		Gen	—
1N3223	Si-Di	S, 150V, 800ns	31a	USA	BA196..196, BAV20..21, BAX15..17, ++
1N3225	Ge-Di	S, 40V, 0,03A, <500ns	31a	Idc, Sem	AAY26, 1N276, 1N631, 1N633
1N3227	Si-Di	Gl, Uni, 100V, 0,5A	31a	Idc, Sem	BY126..127, BY133..135, 1N4002..07, ++
1N3228	Si-Di	=1N3227: 200V	31a		BY126..127, BY133..134, 1N4003..07, ++
1N3229	Si-Di	=1N3227: 400V	31a		BY126..127, BY133..134, 1N4004..07, ++
1N323(A)	Si-Di	Gl, 50V, 0,4A	34a	USA	BA157..159, BY126..127, 1N4001..07, ++
1N3230	Si-Di	=1N3227: 600V	31a		BY126..127, BY133..134, 1N4005..07, ++
1N3231	Si-Di	=1N3227: 800V	31a		BY127, BY133, GP10Q, 1N4006..07, ++
1N3232	Si-Di	=1N3227: 1000V	31a		BY127, BY133, GP10Q, 1N4007, ++
1N3233	Si-Di	=1N3227: 1200V	31a		BY127, BY133, EM513, GP10Q, ++
1N3234	Si-Di	=1N3227: 1500V	31a		BY269, GP10W, DM513, EM516, ++
1N3235	Si-Di	=1N3227: 1800V	31a		DM518
1N3236	Si-Di	=1N3227: 2000V	31a		—
1N3237	Si-Di	Gl, Uni, 50V, 0,75A	31a	USA	BY126..127, BY133..135, 1N4001..07, ++
1N3238	Si-Di	=1N3237: 100V	31a		BY126..127, BY133..135, 1N4002..07, ++
1N3239	Si-Di	=1N3237: 200V	31a		BY126..127, BY133..134, 1N4003..07, ++
1N324(A)	Si-Di	=1N323: 100V	34a	USA	BA157..159, BY126..127, 1N4002..07, ++

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1N3240	Si-Di	=1N3237: 400V	31a		BY126..127, BY133..134, 1N4004..07, ++
1N3241	Si-Di	=1N3237: 600V	31a		BY126..127, BY133..134, 1N4005..07, ++
1N3242	Si-Di	=1N3237. 800V	31a		BY127, BY133, GP10Q, 1N4006..07, ++
1N3243	Si-Di	=1N3237: 1000V	31a		BY127, BY133, GP10Q, 1N4007, ++
1N3244	Si-Di	=1N3237: 1200V	31a		BY127, BY133, EM513, GP10Q, ++
1N3245	Si-Di	=1N3237: 1500V	31a		BY269, DM513, EM516, GP10W, ++
1N3246	Si-Di	GI, Uni, 50V, 1A	31a	USA	BY126..127, BY133..135, 1N4001..07, ++
1N3247	Si-Di	=1N3246: 100V	31a		BY126..127, BY133..135, 1N4002..07, ++
1N3246	Si-Di	=1N3246: 200V	31a		BY126..127, BY133..134, 1N4003. 07, ++
1N3249	Si-Di	=1N3246: 400V	31a		BY126..127, BY133..134, 1N4004..07, ++
1N325(A)	Si-Di	=1N323: 200V	34a	USA	BA157..159, BY126..127, 1N4003..07, ++
1N3250	Si-Di	=1N3246: 600V	31a		BY126..127, BY133 .134, 1N4005..07, ++
1N3251	Si-Di	=1N3246: S00V	31a		BY127, BY133, BY227, 1N4006..07, ++
1N3252	Si-Di	=1N3246: 1000V	31a		BY127, BY133, BY227, 1N4007, ++
1N3253	Si-Di	=1N3193: Iso	34a	USA, Rca, Tos	→1N3193
1N3254	Si-Di	=1N3194: Iso	34a		→1N3194
1N3255	Si-Di	=1N3195: Iso	34a		→1N3195
1N3256	Si-Di	=1N3196: Iso	34a		→1N3195
1N3257	Si-Di	SS, 80V, <3ns	31a	USA	BA219, BAW62, BAX95, 1N4148..49, ++
1N3256	Si-Di	SS, 80V, <4ns	31a	USA	BA219, BAW62, BAX95, 1N4146..49, ++
1N326(A)	Si-Di	=1N323: 350V	34a	USA	BA157..159, BY126..127, 1N4004..07, ++
1N3280	Si-Di	GL-L, 50V, 160A(Tc=125°)	73a	USA, Gen	1N4567..95
1N3280R..3276R	Si-Di	=1N3280..3276.	73b		1N4567R..4595R
1N3261	Si-Di	=1N3280: 100V	73a		1N4567..96
1N3262	Si-Di	=1N3260: 150V	73a		1N4588..95
1N3263	Si-Di	=1N3280: 200V	73a		1N4588..96
1N3264	Si-Di	=1N3260: 250V	73a		1N4589..96
1N3265	Si-Di	=1N3260: 300V	73a		1N4589..96
1N3266	Si-Di	=1N3260: 350V	73a		1N4590..96
1N3267	Si-Di	=1N3260: 400V	73a		1N4590..96
1N3266	Si-Di	=1N3260: 500V	73a		1N4591..96
1N3269	Si-Di	=1N3260: 600V	73a		1N4592..96
1N327(A)	Si-Di	=1N323: 500V	34a	USA	BA156..159, BY126..127, 1N4005..07, ++
1N3270	Si-Di	=1N3260: 700V	73a		1N4593..96
1N3271	Si-Di	=1N3260: 600V	73a		1N4593. 96
1N3272	Si-Di	=1N3260: 900V	73a		1N4594..96
1N3273	Si-Di	=1N3260: 1000V	73a		1N4594..96
1N3274	Si-Di	=1N3260: 1200V	73a		1N4595..96
1N3275	Si-Di	=1N3260: 1400V	73a		1N4596
1N3276	Si-Di	=1N3260: 1600V	73a		—
1N3277	Si-Di	GI, Uni, 200V, 0,75A	31a	USA	BY126..127, BY133..134, 1N4003..07, ++
1N3278	Si-Di	=1N3277: 400V	31a		BY126..127, BY133..134, 1N4004..07, ++
1N3279	Si-Di	=1N3277: 600V	31a		BY126..127, BY133..134, 1N4005..07, ++
1N328(A)	Si-Di	=1N323: S50V	34a	USA	BA159, BY127, BY133, 1N4007, ++
1N3280	Si-Di	=1N3278: 800V	31a		BY127, BY133, BY227, 1N4006..07, ++
1N3261	Si-Di	=1N3278: 1000V	31a		BY127, BY133, BY227, 1N4007, ++
1N3262	Si-Di	GI, Uni, 1000V, 0,1A	31a	USA, Mot, Tho	BY203/12, RGP01-10, SHG1, 1N5161, ++
1N3263	Si-Di	=1N3262: 1500V	31a		BY203/16, RGP01-16, SHG1,5, 1N5161, ++
1N3264	Si-Di	=1N3282: 2000V	31a		BY203/20, HVG2, SHG2, 1N5161, ++
1N3285	Si-Di	=1N3282: 2500V	31a		HVG3, SHG2,5, 1N1733, 1N5181, ++
1N3266	Si-Di	=1N3282: 3000V	31a		HVG3, GP02-30, 1N1733, 1N5161, ++
1N3267(A)	Ge-S1	0,26V, 0,25W	31a	USA, Itt	—
1N3268(A)	Si-Di	GI-L, 100V, 100A(Tc=130°)	73a	Gen, Inr, ++	—
1N3288R..3297R	Si-Di	=1N3268..3297:	73b		DS65-01C..-12C
1N3269(A)	Si-Di	=1N3268: 200V	73a		—
1N329(A)	Si-Di	=IN323: 1000V	34a	USA	BA159, BY127, BY133, 1N4007, ++
1N3290(A)	Si-Di	=1N3288: 300V	73a		—
1N3291(A)	Si-Di	=1N3288: 400V	73a		—
1N3292(A)	Si-Di	=1N3288: 500V	73a		—
1N3293(A)	Si-Di	=1N3288: 600V	73a		—
1N3294(A)	Si-Di	=1N3268: 600V	73a		—
1N3295(A)	Si-Di	=1N3288: 1000V	73a		—
1N3296(A)	Si-Di	=1N3266: 1200V	73a		—
1N3297(A)	Si-Di	=1N32683: 1400V	73a		—
1N3298	Si-Di	S, 80V, <200ns	31a	USA	BAV16..21, BAX15..17, BAY42..43, ++
1N3298A	Si-Di	=1N3286: 70V, 0,3A, <20ns	31a		BAV18..21, BAX15..17, BAY42..43, ++

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1N3299	Trigger-Di	Ub=36..44V, Ib<0,125mA, Itsm=10A	31a	Mdc,Spe	—
1N330	Si-Di	Uni, 32V	31a	USA	BA 127..128, BA 147/50, BA 222, ++
1N3300	Trigger-Di	Ub=14,4..21,6V, Ib<1µA, Itsm=50A	31a	Mdc,Spe	—
1N3300A	Trigger-Di	=1N3300: Ub=16,2..19,8V	31a		—
1N3301	Trigger-Di	=1N3300: Ub=17,6..29,4V	31a		—
1N3301A	Trigger-Di	=1N3300: Ub=19,8..24,2V	31a		—
1N3302	Trigger-Di	=1N3300: Ub=21,6..32,4V	31a		—
1N3302A	Trigger-Di	=1N3300: Ub=24,3..29,7V	31a		—
1N3303	Trigger-Di	=1N3300: Ub=26,4..39,6V	31a		—
1N3303A	Trigger-Di	=1N3300: Ub=29,7..36,3V	31a		—
1N3304	Trigger-Di	=1N3300: Ub=31,2..46,6V	31a		—
1N3304A	Trigger-Di	=1N3300: Ub=35,1..42,9V	31a		—
1N3305	Z-Di	6,8V, 20%, 50W(Tc=75°)	32b	USA,Sie,Tho	BZY91/
1N3305A..3350A	Z-Di	=1N3305..3350: 10%	32b		—
1N3305B..3350B	Z-Di	=1N3305..3350: 5%	32b		—
1N3305R..3350R	Z-Di	=1N3305..3350:	32a		—
1N3306	Z-Di	=1N3305: 7,5V	32b		—
1N3307	Z-Di	=1N3305: 6,2V	32b		—
1N3308	Z-Di	=1N3305: 9,1V	32b		—
1N3309	Z-Di	=1N3305: 10V	32b		—
1N331	Si-Di	Uni, 16V	31a	USA	BA 127..123, BA 147/25, BA 222, ++
1N3310	Z-Di	=1N3305: 11V	32b		—
1N3311	Z-Di	=1N3305: 12V	32b		—
1N3312	Z-Di	=1N3305: 13V	32b		—
1N3313	Z-Di	=1N3305: 14V	32b		—
1N3314	Z-Di	=1N3305: 15V	32b		—
1N3315	Z-Di	=1N3305: 16V	32b		—
1N3316	Z-Di	=1N3305: 17V	32b		—
1N3317	Z-Di	=1N3305: 18V	32b		—
1N3318	Z-Di	=1N3305: 19V	32b		—
1N3319	Z-Di	=1N3305: 20V	32b		—
1N332	Si-Di	Gl-L, 400V, 1,2A	32a	USA	BYX 38/600, BYX 39/600
1N3320	Z-Di	=1N3305: 22V	32b		—
1N3321	Z-Di	=1N3305: 24V	32b		—
1N3322	Z-Di	=1N3305: 25V	32b		—
1N3323	Z-Di	=1N3305: 27V	32b		—
1N3324	Z-Di	=1N3305: 30V	32b		—
1N3325	Z-Di	=1N3305: 33V	32b		—
1N3326	Z-Di	=1N3305: 36V	32b		—
1N3327	Z-Di	=1N3305: 39V	32b		—
1N3328	Z-Di	=1N3305: 43V	32b		—
1N3329	Z-Di	=1N3305: 45V	32b		—
1N333	Si-Di	=1N332: 0,6A	32a	USA	BYX 38/600, BYX 39/600
1N3330	Z-Di	=1N3305: 47V	32b		—
1N3331	Z-Di	=1N3305: 50V	32b		—
1N3332	Z-Di	=1N3305: 51V	32b		—
1N3333	Z-Di	=1N3305: 52V	32b		—
1N3334	Z-Di	=1N3305: 56V	32b		—
1N3335	Z-Di	=1N3305: 62V	32b		—
1N3336	Z-Di	=1N3305: 68V	32b		—
1N3337	Z-Di	=1N3305: 75V	32b		—
1N3338	Z-Di	=1N3305: 82V	32b		—
1N3339	Z-Di	=1N3305: 91V	32b		—
1N334	Si-Di	=1N332: 300V	32a	USA	BYX 38/300, BYX 39/600
1N3340	Z-Di	=1N3305: 100V	32b		—
1N3341	Z-Di	=1N3305: 105V	32b		—
1N3342	Z-Di	=1N3305: 110V	32b		—
1N3343	Z-Di	=1N3305: 120V	32b		—
1N3344	Z-Di	=1N3305: 130V	32b		—
1N3345	Z-Di	=1N3305: 140V	32b		—
1N3346	Z-Di	=1N3305: 150V	32b		—
1N3347	Z-Di	=1N3305: 160V	32b		—
1N3346	Z-Di	=1N3305: 175V	32b		—
1N3349	Z-Di	=1N3305: 180V	32b		—
1N335	Si-Di	=1N332: 300V, 0,6A	32a	USA	BYX 38/300, BYX 39/600
1N3350	Z-Di	=1N3305: 200V	32b		—

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1N3353	Ge-Di	Backward-Di	31	Phc	—
1N3354	Si-Di	Gl, 10V, 3A(Tc=55°+C3261)	32	Cri	BYX38/300, BYX39/600
1N3355	Si-Di	=1N3354: 15V	32		BYX38/300, BYX39/600
1N3356	Si-Di	=1N3354: 25V	32		BYX38/300, BYX39/600
1N3357	Si-Di	=1N3354: 50V	32		BYX38/300, BYX39/600
1N3358	Si-Di	=1N3354: 75V	32		BYX38/300, BYX39/600
1N3359	Si-Di	=1N3354: 100V	32		BYX38/300, BYX39/600
1N336	Si-Di	=1N332: 200V	32a	USA	BYX38/300, BYX39/600
1N3360	Si-Di	=1N3354: 150V	32		BYX38/300, BYX39/600
1N3361	Si-Di	=1N3354: 200V	32		BYX38/300, BYX39/600
1N3362	Si-Di	=1N3354: 300V	32		BYX38/300, BYX39/600
1N3363	Si-Di	=1N3354: 400V	32		BYX38/600, BYX39/600
1N3364	Si-Di	=1N3354: 500V	32		BYX38/600, BYX39/600
1N3365	Si-Di	=1N3354: 600V	32		BYX39/600, BYX39/600
1N3366	Si-Di	=1N3354: 700V	32		BYX38/900, BYX39/600
1N3367	Si-Di	=1N3354: 800V	32		BYX38/900, BYX39/600
1N3368	Si-Di	=1N3354: 900V	32		BYX38/900, BYX39/1000
1N3369	Si-Di	=1N3354: 1000V	32		BYX38/1200, BYX39/1000
1N337	Si-Di	=1N332: 200V, 0,6A	32a	USA	BYX38/300, BYX39/600
1N3370	Si-Di	=1N3354: 1200V	32		BYX38/1200, BYX39/1200
1N3371	Si-Di	=1N3354: 1500V	32		—
1N3372	Si-Di	Gl-L, 10V, 20A(Tc=100°)	75	Cri	DS25-01A, 1N3491..95
1N3373	Si-Di	=1N3372: 25V	75		DS25-01A, 1N3491..95
1N3374	Si-Di	=1N3372: 50V	75		DS25-01A, 1N3491..95
1N3375	Si-Di	=1N3372: 100V	75		DS25-01A, 1N3492..95
1N3376	Si-Di	=1N3372: 150V	75		DS25-02A, 1N3493..95
1N3377	Si-Di	=1N3372: 200V	75		DS25-02A, 1N3493..95
1N3378	Si-Di	=1N3372: 300V	75		DS25-03A, 1N3494..95
1N3379	Si-Di	=1N3372: 400V	75		DS25-05A, 1N3495
1N338	Si-Di	Gl-L, 100V, 3A	32a	USA	BYX38/300, BYX39/600
1N3360	Si-Di	=1N3372: 500V	75		DS25-05A
1N3361	Si-Di	Gl, 15V		Cri	—
1N3362	Si-Di	=1N3361: 30V			—
1N3363	Si-Di	=1N3381: 50V			—
1N3364	Si-Di	=1N3381: 75V			—
1N3385	Si-Di	=1N3381: 100V			—
1N3368	Si-Di	=1N3361: 150V			—
1N3387	Si-Di	=1N3361: 200V			—
1N3368	Si-Di	=1N3361: 250V			—
1N3389	Si-Di	=1N3361: 300V			—
1N339	Si-Di	=2N336: 1,2A	32a	U6A	BYX38/300, BYX39/600
1N3390	Si-Di	=1N3361: 400V			—
1N3391	Si-Di	=1N3381: 500V			—
1N3392	Z-Di	1,5V, 10%, 0,5W		Cri,Idc	BZX55/.., BZX83/.., ZPD.., 1N5221..61, ++
1N3393	Z-Di	=1N3392: 1,8V			—
1N3394	Z-Di	=1N3392: 2,2V			—
1N3395	Z-Di	=1N3392: 2,7V			—
1N3396	Z-Di	=1N3392: 3,3V			—
1N3397	Z-Di	=1N3392: 3,9V			—
1N3396	Z-Di	=1N3392: 4,7V			—
1N3399	Z-Di	=1N3392: 5,6V			—
1N34(A)	Ge-Di	Uni, Dem, 75V, 50mA	31a	EUR,USA,Nec	AA113, 1N60
1N340	Si-Di	=2N336: 0,6A	32a	USA	BYX38/300, BYX39/600
1N3400	Z-Di	=1N3392: 6,8V			—
1N3401	Z-Di	=1N3392: 8,2V			—
1N3402	Z-Di	=1N3392: 10V			—
1N3403	Z-Di	=1N3392: 12V			—
1N3404	Z-Di	=1N3392: 15V			—
1N3405	Z-Di	=1N3392: 18V			—
1N3406	Z-Di	=1N3392: 22V			—
1N3407	Z-Di	=1N3392: 27V			—
1N3406	Z-Di	=1N3392: 33V			—
1N3409	Z-Di	=1N3392: 39V			—
1N341	Si-Di	=2N338: 400V, 1,2A	32a	USA	BYX38/600, BYX39/600
1N3410	Z-Di	=1N3392: 47V			—
1N3411	Z-Di	6,2V, 10%, 0,5W		Cri,Idc	BZX55/.., BZX83/.., ZPD.., 1N5234..81, ++

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1N3412	Z-Di	=1N3411: 6,8V			—
1N3413	Z-Di	=1N3411: 7,5V			—
1N3414	Z-Di	=1N3411: 8,2V			—
1N3415	Z-Di	=1N3411: 10V			—
1N3416	Z-Di	=1N3411: 12V			—
1N3417	Z-Di	=1N3411: 15V			—
1N3418	Z-Di	=1N3411: 18+C3332V			—
1N3419	Z-Di	=1N3411: 22V			—
1N342	Si-Di	=2N338: 400V, 0,6A	32a	USA	BYX 38/600, BYX 39/600
1N3420	Z-Di	=1N3411: 27V			—
1N3421	Z-Di	=1N3411: 30V			—
1N3422	Z-Di	=1N3411: 33V			—
1N3423	Z-Di	=1N3411: 39V			—
1N3424	Z-Di	=1N3411: 47V			—
1N3425	Z-Di	=1N3411: 56V			—
1N3426	Z-Di	=1N3411: 68V			—
1N3427	Z-Di	=1N3411: 82V			—
1N3428	Z-Di	=1N3411: 100V			—
1N3429	Z-Di	=1N3411: 120V			—
1N343	Si-Di	=2N338: 300V, 1,2A	32a	USA	BYX 38/600, BYX 39/600
1N3430	Z-Di	=1N3411: 150V			—
1N3431	Z-Di	=1N3411: 180V			—
1N3432	Z-Di	=1N3411: 220V			—
1N3433	Z-Di	8,2V, 2W			BZD23/.., BZV47/.., BZX70/..
1N3434	Z-Di	=1N3433: 10V			—
1N3435	Z-Di	=1N3433: 12V			—
1N3436	Z-Di	=1N3433: 15V			—
1N3437	Z-Di	=1N3433: 18V			—
1N3438	Z-Di	=1N3433: 22V			—
1N3439	Z-Di	=1N3433: 27V			—
1N344	Si-Di	Gl-L, 300V, 0,6A	32a	USA	BYX 38/300, BYX 38/600
1N3440	Z-Di	=1N3433: 33V			—
1N3441	Z-Di	=1N3433: 39V			—
1N3442	Z-Di	=1N3433: 47V			—
1N3443	Z-Di	8,2V, 10%, 2W			BZD23/.., BZV47/.., BZX70/..
1N3444	Z-Di	=1N3443: 6,8V			—
1N3445	Z-Di	=1N3443: 8,2V			—
1N3446	Z-Di	=1N3443: 10V			—
1N3447	Z-Di	=1N3443: 12V			—
1N3448	Z-Di	=1N3443: 15V			—
1N3449	Z-Di	=1N3443: 18V			—
1N345	Si-Di	=1N344: 200V, 1,2A	32a	USA	BYX 38/300, BYX 39/600
1N3450	Z-Di	=1N3443: 22V			—
1N3451	Z-Di	=1N3443: 27V			—
1N3452	Z-Di	=1N3443: 30V			—
1N3453	Z-Di	=1N3443: 33V			—
1N3454	Z-Di	=1N3443: 39V			—
1N3455	Z-Di	=1N3443: 47V			—
1N3456	Z-Di	=1N3443: 56V			—
1N3457	Z-Di	=1N3443: 68V			—
1N3458	Z-Di	=1N3443: 82V			—
1N3459	Z-Di	=1N3443: 100V			—
1N346	Si-Di	=1N344: 200V, 0,6A	32a	USA	BYX 38/300, BYX 38/600
1N3460	Z-Di	=1N3443: 120V			—
1N3481	Z-Di	=1N3443: 150V			—
1N3462	Z-Di	=1N3443: 180V			—
1N3463	Z-Di	=1N3443: 220V			—
1N3464	Si-Di	kV-Gl, 12kV, 0,06A	31a	Gen,Sol	1N3052
1N3465	Ge-Di	Uni, 80V, 75mA	31a	USA,Itt	AA117..118, AA132..134, 1N34, 1N54, ++
1N3468	Ge-Di	Uni, 40V, 75mA	31a	USA,Itt	AA117..118, AA132..134, 1N34, 1N54, ++
1N3467	Ge-Di	SS, 18V, <2ns	31a	USA,Itt	—
1N3488	Ge-Di	SS, 18V, <2ns	31a	USA,Itt	—
1N3489	Ge-Di	Uni, 35V, 85mA	31a	USA,Itt	AA135..138, 1N634..635
1N347	Si-Di	=1N344: 100V, 3A	32a	USA	BYX 38/300, BYX 39/600
1N3470	Ge-Di	Uni, 35V, 85mA	31a	USA	AA135..139, 1N634..635
1N3471	Si-Di	SS, 40V, 0,04A, <2ns		Idc,Wec	BA218, BAX13, BAX91, 1N4148..49, ++

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1N3473	Si-Di	GI, 200V			—
1N3474	Si-Di	=1N3473: 400V			—
1N3475	Si-Di	=1N3473: 600V			—
1N3476	Si-Di	=1N3473: 600V			—
1N3477	Z-Di	2,2V, 10%, 0,25W	31a	Idc,Gie	BZX55/C2V4, BZX79/C2V4, 1N5221
1N3477A	Z-Di	=1N3477: 5%	31a		—
1N3478	Si-Di	GI, Uni, 200V			BY126..127, BY133..134, 1N4003..07, ++
1N3479	Si-Di	=1N3476: 400V			BY126..127, BY133..134, 1N4004..07, ++
1N346	Si-Di	=1N344: 100V, 1,2A	32a	USA	BYX38/300, BYX39/600
1N3460	Si-Di	=1N3476: 600V			BY126..127, BY133..134, 1N4005..07, ++
1N3461	Ge-Di	UHF, X-Band-S	Koax	Phc	—
1N3482	Ge-Di	UHF, X-Band-S	Koax	Phc	—
1N3463	Ge-Di	Uni, 8V	31a	USA	—
1N3464	Ge-Di	Uni, 75V	31a	Idc,Sem	AA117..118, AA132..133
1N3465	Si-Di	S, 175V, <50ns	31a	Cri	BA197..198, BAV20..21, 1N3070, ++
1N3486	Si-Di	GI, 1000V, 0,4A	34a	USA	BA159, BY127, BY133, BY204/10, ++
1N3487	Si-Di	=1N3486: 1200V	34a		BY127, BY133, BYX94..95, GP10Q, ++
1N3486	Si-Di	VHF-Tuning	31a	Gie,Trw	—
1N3469(A)	Trigger-Di	Ub=16..24V, Ib<0,125mA, Itsm=10A	31a	Mdc,Spe	—
1N349	Si-Di	=1N344: 100V, 0,6A	32a	USA	BYX38/300, BYX39/600
1N3490	Trigger-Di	=1N3489	31a		—
1N3491	Si-Di	GI-L, 50V, 25V(Tc=130°+C3458)	75a	USA,Mot	SSiE1205..1240, 1N3659..3665
1N3491R...3495R	Si-Di	=1N3491..3495:	75b		DS25-..A, SSiE1105..40, 1N3659R..65R
1N3492	Si-Di	=1N3491: 100V	75a		SSiE1210..1240, 1N3660..3665
1N3493	Si-Di	=1N3491: 200V	75a		SSiE1220..1240, 1N3661..3665
1N3494	Si-Di	=1N3491: 300V	75a		SSiE1220..1240, 1N3662..3665
1N3495	Si-Di	=1N3491: 400V	75a		SSiE1230..1240, 1N3663..3665
1N3496	Ref-Di	6,2V, 5%, 0,25W	31a	USA,Sie,Tho	BZV11, BZV28, BZX91, 1N4581
1N3497	Ref-Di	6,2V, 5%, 0,25W	31a		BZV12, BZV29, BZX92, 1N4582
1N3498	Ref-Di	6,2V, 5%, 0,25W	31a		BZV13, BZV30, BZX93, 1N4583
1N3499	Ref-Di	6,2V, 5%, 0,25W	31a		BZV14, BZV31, BZX94, 1N4584
1N35	Ge-Di	FM-Dem, gep, 75V, 22,5mA	2x31a	USA,Nec,Tho	AA113, 1N34
1N350	Si-Di	Uni, 70V, 15mA	2c	USA	BA147/100, BAY19..21, BAY45..46, ++
1N3500	Ref-Di	6,2V, 5%, 0,25W	31a		BZV10, BZV27, BZX90, 1N4580
1N3501	Ref-Di	6,35V, 2%, 0,25W	31a	USA,Sie	1N4890
1N3502	Ref-Di	6,35V, 2%, 0,25W	31a		1N4891
1N3503(A)	Ref-Di	6,35V, 2%, 0,25W	31a		1N4890..95
1N3504(A)	Ref-Di	6,35V, 2%, 0,25W	31a		1N4690..95
1N3506	Z-Di	3,3V, 5%, 0,4W	31a	USA,Sie,Tix	BZX55/..., BZX83/..., ZPD..., 1N5226..61,...
1N3507	Z-Di	=1N3506: 3,6V	31a		—
1N3506	Z-Di	=1N3506: 3,9V	31a		—
1N3509	Z-Di	=1N3506: 4,3V	31a		—
1N351	Si-Di	=1N350: 120V	2c	USA	BA147/150, BAY20..21, BAY45..46, ++
1N3510	Z-Di	=1N3506: 4,7V	31a		—
1N3511	Z-Di	=1N3506: 5,1V	31a		—
1N3512	Z-Di	=1N3506: 5,6V	31a		—
1N3513	Z-Di	=1N3506: 6,2V	31a		—
1N3514	Z-Di	=1N3506: 6,6V	31a		—
1N3515	Z-Di	=1N3506: 7,5V	31a		—
1N3516	Z-Di	=1N3506: 6,2V	31a		—
1N3517	Z-Di	=1N3506: 9,1V	31a		—
1N3518	Z-Di	=1N3506: 10V	31a		—
1N3519	Z-Di	=1N3506: 11V	31a		—
1N352	Si-Di	=1N350: 170V	2c	USA	BA147/230, BAY20..21, BAY46, ++
1N3520	Z-Di	=1N3506: 12V	31a		—
1N3521	Z-Di	=1N3506: 13V	31a		—
1N3522	Z-Di	=1N3506: 15V	31a		—
1N3523	Z-Di	=1N3506: 16V	31a		—
1N3524	Z-Di	=1N3506: 16V	31a		—
1N3525	Z-Di	=1N3506: 20V	31a		—
1N3526	Z-Di	=1N3506: 22V	31a		—
1N3527	Z-Di	=1N3506: 24V	31a		—
1N3528	Z-Di	=1N3506: 27V	31a		—
1N3529	Z-Di	=1N3506: 30V	31a		—
1N353	Si-Di	=1N350: 225V	2c	USA	BA147/300, BAY21, BAY48, BAY88, ++
1N3530	Z-Di	=1N3506: 33V	31a		—

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1N3531	Z-Di	=1N3506: 36V	31a		—
1N3532	Z-Di	=1N3506: 39V	31a		—
1N3533	Z-Di	=1N3506: 43V	31a		—
1N3534	Z-Di	=1N3506: 47V	31a		—
1N3535	Si-Di	200V			—
1N3536	Si-Di	70V			—
1N3537	Z-Di	12V, 10%, 1W	34a	USA	BZW22/C12, BZX61/C12, ZPY12, 1N5927, ++
1N3539	Si-Di	150V			—
1N3539(A)	Si-Di	Backward-Di	31	Msc	—
1N354	Si-Di	=1N350: 325V	2c	USA	BA147/300, BAY21, BAY46, BAY88, ++
1N3540(A)	Si-Di	Backward-Di	31	Msc	—
1N3541(A)	Si-Di	Backward-Di	31	Msc	—
1N3542(A)	Si-Di	Backward-Di	31	Msc	—
1N3543(A)	Si-Di	Backward-Di	31	Msc	—
1N3544	Si-Di	Gl, Uni, 100V, 0,6A	31a	USA	BY126..127, BY133..134, 1N4002..07, ++
1N3545	Si-Di	=1N3544: 200V	31a		BY126..127, BY133..134, 1N4003..07, ++
1N3546	Si-Di	=1N3544: 300V	31a		BY126..127, BY133..134, 1N4004..07, ++
1N3547	Si-Di	=1N3544: 400V	31a		BY126..127, BY133..134, 1N4004..07, ++
1N3546	Si-Di	=1N3544: 500V	31a		BY126..127, BY133..134, 1N4005..07, ++
1N3549	Si-Di	=1N3544: 600V	31a		BY126..127, BY133..134, 1N4005..07, ++
1N355	Ge-Di	Uni, 80V, 50mA	31a	USA	AA117..116, AA132..134, 1N34, 1N54, ++
1N3550	Si-Di	S, 180V, 0,08A, <1,5µs	31a	USA	BA157..159, BA199/250, BAY46, ++
1N3551	Si-Di	VHF-Tuning	31a	Trw	—
1N3552(A)	Si-Di	VHF-Tuning	31a	Trw	—
1N3553	Ref-Di	0,25V, 0,25W	31a	USA	—
1N3554	Si-Di	VHF-Tuning	31a	Trw	—
1N3555	Si-Di	VHF-Tuning	31a	Trw	—
1N3556	Si-Di	VHF-Tuning	31a	Trw	—
1N3557	Si-Di	VHF-Tuning	31a	Trw	—
1N3558	Si-Di	=2x1N751 gep			→1N751
1N3559	Ge-Di	Uni, 24V	31a	Idc, Sem	AA139, 1N270
1N3560	Ge-Di	Tunnel-Di	31	Phc	—
1N3561	Ge-Di	Tunnel-Di	31	Phc	—
1N3562	Ge-Di	Tunnel-Di	31	Phc	—
1N3563	Si-Di	Gl, 1000V, 0,4A	34a	USA, Rca	BA159, BY127, BY133, 1N4007, ++
1N3564	Ge-Di	Uni, gep, 15V	31a	Idc, Sem	AA112..113, AA116, 1N34, 1N54, 1N60, ++
1N3565	Si-Di	6V, 2A	32	USA	—
1N3566	Si-Di	Gl-L, 800V, 1A	32a	Cri	BYX38/900, BYX39/800
1N3567	Si-Di	Min, 75V, 0,06A, <2ns	31a	USA	(BA218, BAX13, BAX91, 1N4146..49, ++)
1N3568	Si-Di	Min, 80V, <4ns	31a	USA	(BA218, BAX13, BAX91, 1N4146..49, ++)
1N3569	Si-Di	Gl-L, 100V, 3,5A(Tc=85°)	32a	USA, Cen, Mot	BYX38/300, BYX39/600
1N3570	Si-Di	=1N3569: 200V	32a		BYX38/300, BYX39/600
1N3571	Si-Di	=1N3569: 300V	32a		BYX38/300, BYX39/600
1N3572	Si-Di	=1N3569: 400V	32a		BYX38/600, BYX39/600
1N3573	Si-Di	=1N3569: 500V	32a		BYX36/600, BYX39/600
1N3574	Si-Di	=1N3569: 600V	32a		BYX38/600, BYX39/600
1N3575	Si-Di	Gl, 80V, 0,15A	34a	USA	BA147/100, BA157..159, BAY19, ++
1N3576	Si-Di	=1N3575: 125V	34a		BA147/150, BA157..159, BAY20, ++
1N3577	Si-Di	=1N3575: 175V	34a		BA147/230, BA157..159, BAY20, ++
1N3578	Si-Di	=1N3575: 225V	34a		BA147/230, BA157..159, BAY21, ++
1N3579	Si-Di	=1N3575: 275V	34a		BA147/300, BA157..159, BAY21, ++
1N356	Si-Di	UHF, L/X-Band-Dem	Koax	USA	—
1N3560(A,B)	Ref-Di	11,7V, 5%, 0,75W	34a	USA, Mot	1N941
1N3581(A,B)	Ref-Di	11,7V, 5%, 0,75W	34a		1N942
1N3562(A,B)	Ref-Di	11,7V, 5%, 0,75W	34a		1N943
1N3563(A,B)	Ref-Di	11,7V, 5%, 0,75W	34a		1N944
1N3584(A,B)	Ref-Di	11,7V, 5%, 0,75W	34a		1N945
1N3585	Si-Di	Gl-L, 50V, 400A(Tc=120°+C3515)	73a	Cri, Ssi	—
1N3568	Si-Di	=1N3585: 100V	73a		—
1N3587	Si-Di	=1N3565: 200V	73a		—
1N3588	Si-Di	=1N3585: 300V	73a		—
1N3589	Si-Di	=1N3565: 400V	73a		—
1N359(A)	Si-Di	Gl, 50V, 0,15A	34a	USA	BA147/50, BAY18..21, 1N4001..07, ++
1N3590	Si-Di	=1N3585: 500V	73a		—
1N3591	Si-Di	=1N3585: 600V	73a		—
1N3592	Ge-Di	S, 30V, 0,05A, <70ns	31a	USA, Tho	AAY27

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1N3593	Si-Di	Min, S, 40V, 005A, 10ns	31a	Idc,Sem	(BA218, BAX13, BAX91, 1N4148..49, ++)
1N3594	Si-Di	Min, S, 60V, 6ns	31a	Idc,Msc,Sem	(BA218, BAX13, BAX91, 1N4148..49, ++)
1N3595	Si-Di	S, 150V, 0,1A, <3μs	31a	USA,Tho	BA147/150, BA157..159, 1N5606..07, ++
1N3596	Si-Di	SS, 20V, 0,075A, <4ns	31a	USA	BA217, BA317, BAY71, 1N4148..49, ++
1N3597	Si-Di	S, 200V, 0,275A, <300ns	31a	USA	BA157..159, BA173, BY206..207, ++
1N3598	Si-Di	SS, 50V, 0,075A, <4ns	31a	USA	BA218, BAX13, BAX91, 1N4148..49, ++
1N3599	Si-Di	S, 150V, <50ns	31a	USA	BA196..198, BAV20..21, BAY80, ++
1N36	Ge-Di	HF-Dem, 36V, 18mA	31a	Kem,Sem,Tho	AA113, AA119, 1N34, 1N60
1N360(A)	Si-Di	=1N359: 100V	34a	USA	BA147/100, BAY19..21, 1N4002..07, ++
1N3600	Si-Di	SS, 50V, 0,2A, <4ns	31a	USA,Tho	BAW62, BAX95, BAY95, 1N4148..49, +
1N3601	Si-Di	SS, 75V, <5ns	31a	USA	BAW62, BAX95, BAW78, 1N4148..49, +
1N3602	Si-Di	SS, 75V, 0,115A, <5ns	31a	USA	BAW62, BAX95, BAW78, 1N4148..49, +
1N3603	Si-Di	=1N3602: 45V	31a		BAW62, BAX95, BAW78, 1N4148..49, +
1N3604	Si-Di	=1N4151	31a	USA,Sie,Tho	→1N4151
1N3605	Si-Di	=1N4152	31a		→1N4152
1N3606	Si-Di	=1N4153	31a		→1N4153
1N3607	Si-Di	=1N4151: Min	31a		→1N4151
1N3608	Si-Di	=1N4152: Min	31a		→1N4152
1N3609	Si-Di	=1N4153: Min	31a		→1N4153
1N361(A)	Si-Di	=1N359: 200V	34a	USA	BA147/230, BAY21, 1N4003..07, ++
1N3611(GP)	Si-Di	GI, 200V, 1A	31a	USA,Sie	BY126..127, BY133..134, 1N4003..07, ++
1N3612(GP)	Si-Di	=1N3611: 400V	31a		BY126..127, BY133..134, 1N4004..07, ++
1N3613(GP)	Si-Di	=1N3611: 600V	31a		BY126..127, BY133..134, 1N4005..07, ++
1N3614(GP)	Si-Di	=1N3611: 600V	31a		BY127, BY133, 1N4006..F354707, ++
1N3615	Si-Di	GI-L, 50V, 16A(Tc=150°)	32a	USA,Mot	BYX25/600, BYX99/600
1N3616	Si-Di	=1N3615: 100V	32a		BYX25/600, BYX99/600
1N3617	Si-Di	=1N3615: 150V	32a		BYX25/600, BYX99/600
1N3618	Si-Di	=1N3615: 200V	32a		BYX25/600, BYX99/600
1N3619	Si-Di	=1N3615: 300V	32a		BYX25/600, BYX99/600
1N362(A)	Si-Di	=1N359: 350V	34a	USA	BAY21, BAY88..90, 1N4003..07, ++
1N3620	Si-Di	=1N3615: 400V	32a		BYX25/600, BYX99/600
1N3621	Si-Di	=1N3615: 500V	32a		BYX25/600, BYX99/600
1N3622	Si-Di	=1N3615: 600V	32a		BYX25/600, BYX99/600
1N3623	Si-Di	=1N3615: 800V	32a		BYX25/600, BYX99/900
1N3624	Si-Di	=1N3615: 1000V	32a		BYX25/1000, BYX99/1200
1N3625	Si-Di	S, 200V, 0,15A	31a	USA	BA157..159, BY204/4, BY206..207, ++
1N3626	Ge-Di	Uni, 50V	31a	USA	AA117..118, AA132..134, 1N34, 1N54, ++
1N3627	Si-Di	VHF-Tuning	31a	Gie,Tdy	—
1N3628	Si-Di	VHF-Tuning	31a	Gie,Tdy	—
1N3629	Si-Di	GI, 100V, 0,75A	31a	Cri,Ssi	BY126..127, BY133..135, 1N4002..07, ++
1N363(A)	Si-Di	=1N359: 500V	34a	USA	BA158..159, BAY89..90, 1N4005..07, ++
1N3630	Si-Di	=1N3629: 200V	31a		BY126..127, BY133..134, 1N4003..07, ++
1N3631	Si-Di	=1N3629: 300V	31a		BY126..127, BY133..134, 1N4004..07, ++
1N3632	Si-Di	=1N3629: 400V	31a		BY126..127, BY133..134, 1N4004..07, ++
1N3633	Si-Di	=1N3629: 500V	31a		BY126..127, BY133..134, 1N4005..07, ++
1N3634	Si-Di	=1N3629: 800V	31a		BY126..127, BY133..134, 1N4005..07, ++
1N3635	Si-Di	=1N3629: 700V	31a		BY127, BY133, BY227, 1N4006..07, ++
1N3636	Si-Di	=1N3629: 800V	31a		BY127, BY133, BY227, 1N4006..07, ++
1N3637	Si-Di	=1N3629: 900V	31a		BY127, BY133, BY227, 1N4007, ++
1N3636	Si-Di	=1N3629: 1000V	31a		BY127, BY133, BY227, 1N4007, ++
1N3639	Si-Di	GI, 200V, 0,75A	34a	USA	BY126..127, BY133..134, 1N4003..07, ++
1N364(A)	Si-Di	=1N359: 850V	34a	USA	BA159, BAY90..91, 1N4007
1N3640	Si-Di	=1N3639: 400V	34a		BY126..127, BY133..134, 1N4004..07, ++
1N3641	Si-Di	=1N3639: 600V	34a		BY126..127, BY133..134, 1N4005..07, ++
1N3642	Si-Di	=1N3639: 800V	34a		BY127, BY133, BY227, 1N4006..07, ++
1N3643	Si-Di	GI, 1000V, 0,25A	31a	USA	BA159, BY127, BY133, 1N4007, ++
1N3644	Si-Di	=1N3643: 1500V	31a		BAY91, BY203/18, BY269, GP10W, ++
1N3645	Si-Di	=1N3643: 2000V	31a		BAY91, BY203/20, GP02-20, MR250-2, ++
1N3646	Si-Di	=1N3643: 2500V	31a		GP02-30, MR250-3, 1N1733A
1N3647	Si-Di	=1N3643: 3000V	31a		GP02-30, MR250-3, 1N1733A
1N3648	Si-Di	kV-GI, 10kV, 0,35A	31a	Cri	—
1N3649	Si-Di	GI-L, 600V, 3,3A(Tc=50°)	32a	USA,Mot,Tix	BYX38/900, BYX39/600
1N3649R...3650R	Si-Di	=1N3649..3650:	32b		BYX38/..R, BYX39/..R
1N365(A)	Si-Di	=1N359: 1000V	34a	USA	BA159, BAY90..91, 1N4007
1N3650	Si-Di	=1N3649: 1000V	32a		BYX39/1200, BYX39/1000
1N3653	Si-Di	SS, 100V, <4ns	31b	USA	(BAV14)

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1N3654	Si-Di	SS, 100V, <4ns	31b	USA	BA219, BAX98
1N3655(A,B)	Si-Di	UHF, S-Band-M		USA	—
1N3656	Si-Di	Gl, Uni, 200V, 0,75A	31a	USA	BY126..127, BY133..134, 1N4003..07,++
1N3657	Si-Di	=1N3656: 400V	31a		BY126..127, BY133..134, 1N4004..07,++
1N3658	Si-Di	=1N3658: 600V	31a		BY126..127, BY133..134, 1N4005..07,++
1N3659	Si-Di	Gl-L, 50V, 30A(Tc=100°)	75a	USA,Mot	SSiE1105..1140
1N3659R...3665R	Si-Di	=1N3659..3665:	75b		SSiE1205..1240
1N3660	Si-Di	=1N3659: 100V	75a		SSiE1110..1140
1N3661	Si-Di	=1N3659: 200V	75a		SSiE1120..1140
1N3662	Si-Di	=1N3659: 300V	75a		SSiE1120..1140
1N3663	Si-Di	=1N3659: 400V	75a		SSiE1130..1140
1N3664	Si-Di	=1N3659: 500V	75a		SSiE1130..1140
1N3665	Si-Di	=1N3659: 600V	75a		SSiE1140
1N3666	Ge-Di	Uni, S, 6+C36050V, 0,07A, <300ns	31a	USA	AAY26, AAZ15, 1N633
1N3667	Si-Di	Gl-L, 500V, 1,5A(Tc=120°)		Cri	—
1N3666	Si-Di	S, 30V, 0,075A, <150ns	31a	USA	BAX85, BAX89..90, BAX94, 1N4146..49++
1N3669	Si-Di	S, 70V, 0,4A, <200ns	31a	USA	BA157..159, BAV15..16, BAX12, ++
1N367	Ge-Di	Uni, 60V	31a	USA	AA117..116, AA132..134, 1N34, 1N54,++
1N3670(A)	Si-Di	Gl-L, 700V, 12A(Tc=150°)	32a	USA,Mot	BYW88/800, BYX60..61, 1N4509..11
1N3670R...3673R	Si-Di	=1N3670..3673:	32b		BYW88/..R, BYX80R..61R
1N3671(A)	Si-Di	=1N3670: 600V	32a		BYW68/600, BYX80..61, 1N4509..11
1N3672(A)	Si-Di	=1N3670: 900V	32a		BYW88/1000, BYX61, 1N4510..11
1N3673(A)	Si-Di	=1N3670: 1000V	32a		BYW68/1000, BYX61, 1N4510..11
1N3675	Z-Di	6,6V, 20%, 0,75W	31a	USA,Mot	BZV8+F36225/.., BZW22/.., ZPY.., 1N3016..51,++
1N3675A...3710A	Z-Di	=1N3675..3710: 10%	31a		—
1N3675B...3710B	Z-Di	=1N3675..3710: 5%	31a		—
1N3676	Z-Di	=1N3675: 7,5V	31a		—
1N3677	Z-Di	=1N3675: 6,2V	31a		—
1N3676	Z-Di	=1N3675: 9,1V	31a		—
1N3679	Z-Di	=1N3675: 10V	31a		—
1N368(A)	Ge-Di	Gl, 200V, 0,1A	34a	USA	—
1N3660	Z-Di	=1N3675: 11V	31a		—
1N3661	Z-Di	=1N3675: 12V	31a		—
1N3682	Z-Di	=1N3675: 13V	31a		—
1N3683	Z-Di	=1N3675: 15V	31a		—
1N3664	Z-Di	=1N3675: 16V	31a		—
1N3685	Z-Di	=1N3675: 16V	31a		—
1N3666	Z-Di	=1N3675: 20V	31a		—
1N3667	Z-Di	=1N3675: 22V	31a		—
1N3666	Z-Di	=1N3675: 24V	31a		—
1N3689	Z-Di	=1N3675: 27V	31a		—
1N369(A)	Si-Di	UHF, L/S/X-Band-Dem	Koax	USA	—
1N3690	Z-Di	=1N3675: 30V	31a		—
1N3691	Z-Di	=1N3675: 33V	31a		—
1N3692	Z-Di	=1N3675: 36V	31a		—
1N3693	Z-Di	=1N3675: 39V	31a		—
1N3694	Z-Di	=1N3675: 43V	31a		—
1N3695	Z-Di	=1N3675: 47V	31a		—
1N3698	Z-Di	=1N3675: 51V	31a		—
1N3697	Z-Di	=1N3675: 56V	31a		—
1N3698	Z-Di	=1N3675: 62V	31a		—
1N3699	Z-Di	=1N3675: 66V	31a		—
1N370	Z-Di	1,65V, 20%, 0,2W	31a	USA	BZX55/.., BZX79/.., ZPD.., 1N5221..36,++
1N3700	Z-Di	=1N3675: 75V	31a,		—
1N3701	Z-Di	=1N3675: 82V	31a		—
1N3702	Z-Di	=1N3675: 91V	31a		—
1N3703	Z-Di	=1N3675: 100V	31a		—
1N3704	Z-Di	=1N3675: 110V	31a		—
1N3705	Z-Di	=1N3675: 120V	31a		—
1N3706	Z-Di	=1N3675: 130V	31a		—
1N3707	Z-Di	=1N3675: 150V	31a		—
1N3706	Z-Di	=1N3675: 160V	31a		—
1N3709	Z-Di	=1N3675: 160V	31a		—
1N371	Z-Di	=1N370: 2,35V, 15%	31a		—
1N3710	Z-Di	=1N3675: 200V	31a		—
1N3711	Si-Di	kV-Gl, 6kV, 0,15A	31a	Cri,Sem	BYX90

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1N3712	Ge-Di	Tunnel-Di	34a	Gen	—
1N3713	Ge-Di	Tunnel-Di	34a	Gen	—
1N3714	Ge-Di	Tunnel-Di	34a	Gen	—
1N3715	Ge-Di	Tunnel-Di	34a	Gen	—
1N3716	Ge-Di	Tunnel-Di	34a	Gen	—
1N3717	Ge-Di	Tunnel-Di	34a	Gen	—
1N3718	Ge-Di	Tunnel-Di	34a	Gen	—
1N3719	Ge-Di	Tunnel-Di	34a	Gen	—
1N372	Z-Di	=1N370 2,9V, 15%	31a		—
1N3720	Ge-Di	Tunnel-Di	31a	Gen	—
1N3721	Ge-Di	Tunnel-Di	34a	Gen	—
1N3722	Si-Di	Min, S. 50V, <10ns	31a	USA	(BA218, BAX13, BAX91, 1N4146..49,++)
1N3723	Si-Di	Gl, 1000V, 0,75A	31a	Sem,Sol	BY127, BY133, BY227, 1N4007,++
1N3724	Si-Di	=1N3723: 1200V	31a		BY127, BY133, BY227, GP10Q,++
1N3725	Si-Di	=1N3723: 1400V	31a		BY400, BY446, EM516, GP10W,++
1N3726	Si-Di	=1N3723: 1600V	31a		BY400, DM513, EM516, GP10Y
1N3727	Si-Di	=1N3723: 1600V	31a		DM516
1N3728	Si-Di	Gl, Uni, 550V, 0,2A	31a	Sem,Ssi	BA156..159, BA199/550, BAY69..90,++
1N3729	Si-Di	Gl, S, 600V, <500ns	31a	Sem,Ssi	BY208/600, BY295/600, BY407,++
1N373	Z-Di	=1N370: 3,5V, 15%	31a		—
1N3730	Si-Di	S, 80V, <15ns	31a	USA	BAW26..27
1N3731	Si-Di	SS, 100V, 0,175A, <3ns	31a	USA	—
1N3732	Z-Di	5,1V, 5%, 1W	34a	USA	BZW22/C5V1, BZX61/C5V1, ZPY5,1, 1N5918,++
1N3733	Si-Di	UHF, S-Band-M	Koax	Miv	—
1N3734	Opto				—
1N3735	Si-Di	Gl-L, 100V, 250A(Tc=130°)	73a	USA,Tho	—
1N3735R..3744R	Si-Di	=1N3735..3744	73b		DS40-..A
1N3736	Si-Di	=1N3735: 200V	73a		—
1N3737	Si-Di	=1N3735: 300V	73a		—
1N3738	Si-Di	=1N3735: 400V	73a		—
1N3739	Si-Di	=1N3735: 500V	73a		—
1N374	Z-Di	=1N370: 4,1V, 10%	31a		—
1N3740	Si-Di	=1N3735: 600V	73a		—
1N3741	Si-Di	=1N3735: 600V	73a		—
1N3742	Si-Di	=1N3735: 1000V	73a		—
1N3743	Si-Di	=1N3735: 1200V	73a		—
1N3744	Si-Di	=1N3735: 1400V	73a		—
1N3745	Si-Di	UHF, X-Band-M	Koax	USA	—
1N3746	Si-Di	UHF, X-Band-M	Koax	USA	—
1N3747	Si-Di	UHF, X-Band-M	Koax	USA	—
1N3748	Si-Di	Gl, 200V, 0,5A	31a	Edl,Sem	BY126..127, BY133..134, 1N4003..07,++
1N3749	Si-Di	=1N3746: 400V	31a		BY126..127, BY133..134, 1N4004..07,++
1N375	Z-Di	=1N370: 4,1V, 5%	31a		—
1N3750	Si-Di	=1N3746: 600V	31a		BY126..127, BY133..134, 1N4005..07,++
1N3751	Si-Di	=1N3746: 800V	31a		BY127, BY133, BY227, 1N4006..07,++
1N3752	Si-Di	=1N3748: 1000V	31a		BY127, BY133, BY227, 1N4007,++
1N3753	Ge-Di	Uni, 55V	31a	Idc,Sem	AA117..116, AA132..134, 1N34, 1N54,++
1N3754	Si-Di	Gl, 100V, 0,125A	2c	Rca,Sem,Tos	BA157..159, BY204/4, BY206..207,++
1N3755	Si-Di	=1N3754: 200V	2c		BA157..159, BY204/4, BY206..207,++
1N3756	Si-Di	=1N3754: 400V	2c		BA157..159, BY204/4, BY206..207,++
1N3757	Si-Di	Gl, 200V, 1A	31a	USA	BY126..127, BY133..134, 1N4003..07,++
1N3756	Si-Di	=1N3757: 400V	31a		BY126..127, BY133..134, 1N4004..07,++
1N3759	Si-Di	=1N3757: 600V	31a		BY126..127, BY133..134, 1N4005..07,++
1N376	Z-Di	=1N370: 4,95V, 5%	31a		—
1N3760	Si-Di	=1N3757: 800V	31a		BY127, BY133, BY227, 1N4006..07,++
1N3761	Si-Di	=1N3757: 1000V	31a		BY127, BY133, BY227, 1N4007,++
1N3762	Si-Di	kV-Gl, 7,5kV, 0,065A	31a	Sem	BYX90, 1N5183
1N3763	Ref-Di	20V, 5%, 1,5W	31a	Idc,Msc,Sie	—
1N3764	Si-Di	kV-Gl, 3kV, 0,4A	31a	USA	1N1733A
1N3765	Si-Di	Gl-L, 700V, 35A(Tc=140°)	32a	USA,Mot,Tho	1N4526
1N3765R...3768R	Si-Di	=1N3765..3766	32ab		D34C/..C
1N3765T...3768T	Si-Di	=1N3765..3768	73a		—
1N3768	Si-Di	=1N3765: 800V	32a		1N4528
1N3767	Si-Di	=1N3765: 900V	32a		1N4529
1N3766	Si-Di	=1N3765: 1000V	32a		1N4529
1N3769	Ge-Di	Uni, 90V	31a	USA	AA117..116, AA132..133

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1N377	Z-Di	=1N370: 5,9V, 5%	31a		—
1N3770	Si-Di	UHF-Tuning		Miv	—
1N3771	Trigger-Di	Ub>170V	31a	Mdc,Spe	—
1N3772	Trigger-Di	Ub=15..25V, Ib<0,4mA, Itsm=10A	31a	Mdc,Spe	—
1N3773	Ge-Di	S, 25V, <40ns	31a	USA	—
1N3774	Ref-Di	1,15V, 2%, 0,34W	31a	Idc,Sem	—
1N3775	Si-Di	GI-L, 1500V, 3,3A(Tc=50°)	32a	USA	—
1N3776	Z-Di	10V, 10%, 6W	32	Cri	BZX98/C10, BZY93/C10, ZL10, 1N2974, ++
1N3777	Si-Di	GI-L, 800V, 35A(Tc=140°)	32a	USA	1N3766..66, 1N4528..30
1N3778	Si-Di	UHF, C/X-Band-Dem	Koax	Mic,Pai	—
1N3779	Ref-Di	6,5V, 3%, 0,4W	31a	Inr,Sie,++	BZV10, BZV27, BZX90, 1N4580
1N378	Z-Di	=1N370: 7,15V, 5%	31a		—
1N3780	Ref-Di	6,5V, 3%, 0,4W	31a		BZV10, BZV27, BZX90, 1N4580
1N3781	Ref-Di	6,5V, 3%, 0,4W	31a		BZV11, BZV28, BZX91, 1N4581
1N3782	Ref-Di	6,5V, 3%, 0,4W	31a		BZV12, BZV29, BZX92, 1N4582
1N3783	Ref-Di	8,5V, 3%, 0,4W	31a		BZV13, BZV30, BZX93, 1N4583
1N3784	Ref-Di	8,5V, 3%, 0,4W	31a		BZV14, BZV31, BZV94, 1N4584
1N3785	Z-Di	8,8V, 20%, 1,5W	2c	USA,Mot	—
1N3765A...3820A	Z-Di	=1N3785..3820: 10%	2c		—
1N3785B...3820B	Z-Di	=1N3785..3820: 5%	2c		—
1N3786	Z-Di	=1N3785: 7,5V	2c		—
1N3787	Z-Di	=1N3785: 8,2V	2c		—
1N3788	Z-Di	=1N3785: 9,1V	2c		—
1N3789	Z-Di	=1N3785: 10V	2c		—
1N379	Z-Di	8,2V, 0,15W	31a	USA	BZX55/.., BZX79/.., ZPD.., 1N5237..81,..
1N3790	Z-Di	=1N3785: 11V	2c		—
1N3791	Z-Di	=1N3785: 12V	2c		—
1N3792	Z-Di	=1N3785: 13V	2c		—
1N3793	Z-Di	=1N3785: 15V	2c		—
1N3794	Z-Di	=1N3785: 16V	2c		—
1N3795	Z-Di	=1N3785: 18V	2c		—
1N3796	Z-Di	=1N3785: 20V	2c		—
1N3797	Z-Di	=1N3785: 22V	2c		—
1N3796	Z-Di	=1N3785: 24V	2c		—
1N3799	Z-Di	=1N3785: 27V	2c		—
1N38	Ge-Di	Uni, 120V, 50mA	31a	USA,Nec,Tho	AA117..118, AA132..133
1N380	Z-Di	=1N379: 10V	31a		—
1N3800	Z-Di	=1N3785: 30V	2c		—
1N3801	Z-Di	=1N3785: 33V	2c		—
1N3802	Z-Di	=1N3785: 38V	2c		—
1N3803	Z-Di	=1N3785: 39V	2c		—
1N3804	Z-Di	=1N3785: 43V	2c		—
1N3805	Z-Di	=1N3785: 47V	2c		—
1N3806	Z-Di	=1N3785: 51V	2c		—
1N3807	Z-Di	=1N3785: 56V	2c		—
1N3806	Z-Di	=1N3785: 62V	2c		—
1N3809	Z-Di	=1N3785: 66V	2c		—
1N381	Z-Di	=1N379: 12V	31a		—
1N3810	Z-Di	=1N3785: 75V	2c		—
1N3811	Z-Di	=1N3785: 82V	2c		—
1N3812	Z-Di	=1N3785: 91V	2c		—
1N3813	Z-Di	=1N3785: 100V	2c		—
1N3814	Z-Di	=1N3785: 110V	2c		—
1N3815	Z-Di	=1N3785: 120V	2c		—
1N3816	Z-Di	=1N3785: 130V	2c		—
1N3817	Z-Di	=1N3785: 150V	2c		—
1N3818	Z-Di	=1N3785: 160V	2c		—
1N3819	Z-Di	=1N3785: 160V	2c		—
1N382	Z-Di	=1N379: 15V	31a		—
1N3820	Z-Di	=1N3785: 200V	2c		—
1N3821	Z-Di	3,3V, 10%, 1W	34a	USA,Sie,Tho	BZW22/.., BZX81/.., ZPY.., 1N5913..22, ++
1N3821A...3830A	Z-Di	=1N3821..3830: 5%	34a		—
1N3822	Z-Di	=1N3821: 3,6V	34a		—
1N3823	Z-Di	=1N3821: 3,9V	34a		—
1N3824	Z-Di	=1N3821: 4,3V	34a		—
1N3825	Z-Di	=1N3821: 4,7V	34a		—

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1N3826	Z-Di	=1N3821:5,1V	34a		—
1N3827	Z-Di	=1N3821:5,6V	34a		—
1N3826	Z-Di	=1N3821:6,2V	34a		—
1N3829	Z-Di	=1N3821:6,8V	34a		—
1N383	Z-Di	=1N379:16V	813		—
1N3830	Z-Di	=1N3821:7,5V	34a		—
1N3831	Trigger-Di	Ub=16..24V, Ib<0,+C3804125mA, Itsm=5A	31a	USA,Itt	4E20.., 4E20M..
1N3832	Trigger-Di	=1N3831: Ub=21..29V	31a		—
1N3833	Trigger-Di	=1N3831: Ub=26..34V	31a		4E30.., 4E30M..
1N3834	Trigger-Di	=1N3831: Ub=31..39V	31a		4E40.., 4E40M..
1N3835	Triggar-Di	=1N3831: Ub=36..44V	31a		4E40.., 4E40M..
1N3838	Trigger-Di	=1N3831: Ub=41..49V	31a		4E50.., 4E50M..
1N3837	Triggar-Di	=1N3831: Ub=46..54V	31a		4E50.., 4E50M..
1N3838	Trigger-Di	=1N3831: Ub=90..110V	31a		4E100.., 4E100M..
1N3838	Trigger-Di	=1N3831: Ub=16..24V	31a		4E20.., 4E20M..
1N384	Z-Di	=1N379:22V	31a		—
1N3840	Trigger-Di	=1N3831: Ub=21..29V	31a		—
1N3841	Trigger-Di	=1N3831: Ub=26..34V	31a		4E30.., 4E30M..
1N3842	Trigger-Di	=1N3831: Ub=31..39V	31a		4E40.., 4E40M.
1N3843	Trigger-Di	=1N3831: Ub=38..44V	31a		4E40.., 4E40M.
1N3844	Trigger-Di	=1N3831: Ub=41..49V	31a		4E50.., 4E50M.
1N3845	Trigger-Di	=1N3831: Ub=46..54V	31a		4E50.., 4E50M..
1N3846	Trigger-Di	=1N3831: Ub=90..110V	31a		4E100.., 4E100M.
1N3847	Ge-Di	Tunnel-Di		Kmc	—
1N3848	Ge-Di	Tunnel-Di		Kmc	—
1N3849	Ge-Di	Tunnel-Di		Kmc	—
1N385	Z-Di	=1N379:27V	31a		—
1N3850	Ge-Di	Tunnel-Di		Kmc	—
1N3851	Ge-Di	Tunnel-Di		Kmc	—
1N3852	Ge-Di	Tunnel-Di		Kmc	—
1N3853	Ge-Di	Tunnel-Di		Kmc	—
1N3854	Ge-Di	Tunnel-Di		Kmc	—
1N3855	Ge-Di	Tunnel-Di		Kmc	—
1N3856	Ge-Di	Tunnel-Di		Kmc	—
1N3857	Ge-Di	Tunnel-Di		Kmc	—
1N3856	Ge-Di	Tunnel-Di		Kmc	—
1N3859	Ge-Di	Tunnel-Di		Kmc	—
1N386	Z-Di	=1N379:33V	31a		—
1N3860	Ge-Di	Tunnel-Di		Kmc	—
1N3861	Ge-Di	Tunnel-Di		Kmc	—
1N3862	Ge-Di	Tunnel-Di		Kmc	—
1N3863	Ge-Di	Tunnel-Di		Kmc	—
1N3864	Si-Di	S, 125V, <900ns	31a	USA	BA173, BAV19..21, BAX15..17,++
1N3865	Ge-Di	Uni, 60V	31a	Idc,Sem	1N270
1N3866	Si-Di	GI, 200V, 1A	31a	USA	BY126..127, BY133..134, 1N4003..07,++
1N3867	Si-Di	=1N3866:400V	31a		BY126..127, BY133..134, 1N4004..07,++
1N3868	Si-Di	=1N3866:600V	31a		BY126..127, BY133..134, 1N4005..07,++
1N3869	Si-Di	GI, 1000V, 0,5A	31a	USA	BA159, BY127, BY133, 1N4007,++
1N387	Z-Di	=1N379:39V	31a		—
1N38+A383770	Si-Di	=1N3879:1500V	31a		BY269, DM513, EM516, GP10W,++
1N3871	Si-Di	=1N3879:2000V, 0,25A	31a		BAY91, BY203/20, SHG2
1N3872	Si-Di	S, 90V, <15ns	31a	USA	BA202..203, BAV16, BAY43
1N3873	Si-Di	SS, 90V, 0,15A, <4ns	31a	USA	BA219, BAW47
1N3874	Si-Di	=1N3879: Iso	32a	USA	—
1N3875	Si-Di	=1N3860: Iso	32a		—
1N3876	Si-Di	=1N3861: Iso	32a		—
1N3877	Si-Di	=1N3862; Iso	32a		—
1N3876	Si-Di	=1N3863: Iso	32a		—
1N3879(A)	Si-Di	GI/S-L, 50V, 6A(Tc=100°), <200ns	32a	USA,Mot,Rca	BYX62/800
1N3879(A)	Si-Di			Phi,Sie,Tho	—
1N3879R...3883R	Si-Di	=1N3879:	32b		BYX62/800R
1N3866	Z-Di	=1N379:47V	31a		—
1N3860(A)	Si-Di	=1N3879:100V	32a		BYX62/800
1N3881(A)	Si-Di	=1N3879:200V	32a		BYX62/800
1N3882(A)	Si-Di	=1N3879:300V	32a		BYX62/800
1N3863(A)	Si-Di	=1N3879:400V	32a		BYX62/800

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1N3884	Si-Di	=1N3889: Iso	32a	USA	—
1N3885	Si-Di	=1N3890: Iso	32a		—
1N3886	Si-Di	=1N3891: Iso	32a		—
1N3887	Si-Di	=1N3892: Iso	32a		—
1N3888	Si-Di	=1N3893: Iso	32a		—
1N3889(A)	Si-Di	Gl/S-L, 50V, 12A(Tc=100°), <200ns	32a	USA,Mot,Rca	BYX62/800
1N3889(A)	Si-Di			Phi,Sie,Tho	—
1N3889R...3893R	Si-Di	=1N3889	32b		BYX62/800R
1N389	Z-Di	=1N379: 56V	31a		—
1N3890(A)	Si-Di	=1N3889: 100V	32a		BYX62/800
1N3891(A)	Si-Di	=1N3889: 200V	32a		BYX62/800
1N3892(A)	Si-Di	=1N3889: 300V	32a		BYX62/800
1N3893(A)	Si-Di	=1N3889: 400V	32a		BYX62/800
1N3894	Si-Di	Gl, Uni, 400V, 0,4A	31a	Sem,Ssi	BA157..159, BY204/4, BY207, ++
1N3895	Si-Di	Gl, Uni, 350V, 0,4A	31a	Sem,Ssi	BA157..159, BY204/4, BY206..207, ++
1N3896	Z-Di	0,775V, 5%, 0,25W	31a	Idc,Sem	—
1N3897	Z-Di	1,5V, 5%, 0,25W	31a	Idc,Sem	—
1N3898	Z-Di	2V, 5%, 0,25W	31a	Idc,Sem	—
1N3899	Si-Di	Gl/S-L, 50V, 20A(Tc=100°), <200ns	32a	USA,Phi,Tho	BYT65/600, 1N3909..13
1N3899R..3903R	Si-Di	=1N3899: 400V	32b		BYT65/600R, 1N3809R..13R
1N39	Ge-Di	Uni, 200V, 50mA	31a	USA,Nec,Tho	—
1N380	Z-Di	=1N379: 68V	81a		—
1N3900	Si-Di	=1N3899: 100V	32a		BYT65/600, 1N3910..13
1N3901	Si-Di	=1N3899: 200V	32a		BYT65/600, 1N3811..13
1N3802	Si-Di	=1N3899: 300V	32a		BYT65/600, 1N3912..13
1N3903	Si-Di	=1N3899: 400V	32a		BYT65/600, 1N3913
1N3904	Si-Di	=1N3899: Iso	32a	Sem,Ssi	1N8914..18
1N3905	Si-Di	=1N3900: Iso	32a		1N3915..18
1N3906	Si-Di	=1N3901: Iso	32a		1N3918..18
1N3907	Si-Di	=1N3902: Iso	32a		1N3917..18
1N3908	Si-Di	=1N3903: Iso	32a		1N3918
1N3909	Si-Di	Gl/S-L, 50V, 30A(Tc=100°), <200ns	32a	USA,Phi,Tho	MR860..866
1N3909R...3913R	Si-Di	=1N3909..3913:	32b		MR864R..868R
1N391	Z-Di	=1N379: 82V	31a		—
1N3910	Si-Di	=1N3909: 100V	32a		MR681..866
1N3911	Si-Di	=1N3909: 200V	32a		MR862..866
1N3912	Si-Di	=1N3909: 300V	32a		MR864..686
1N3813	Si-Di	=1N3909: 400V	32a		MR864..868
1N3914	Si-Di	=1N3909: Iso	32a		—
1N3915	Si-Di	=1N3810: Iso	32a		—
1N3916	Si-Di	=1N3911: Iso	32a		—
1N3917	Si-Di	=1N3812: Iso	32a		—
1N3918	Si-Di	=1N3913: Iso	32a		—
1N3819	Si-Di	Gl-L, 1000V, 5A(Tc=100°)	32a	USA	BYX38/1200, BYX39/1200
1N392	Z-Di	=1N379: 100V	31a		—
1N3920	Si-Di	=1N3919: 1500V	32a		—
1N3921	Si-Di	=1N3919: 2000V	32a		—
1N3922	Si-Di	=1N3919: 2500V	32a		—
1N3923	Si-Di	=1N3919: 3000V	32a		—
1N3924	Si-Di	Gl-L, 1000V, 10A(Tc=100°)	32a	USA	BYX42/1200, BYX98/1200
1N3925	Si-Di	=1N3924: 1500V	32a		—
1N3926	Si-Di	=1N3924: 2000V	32a		—
1N3927	Si-Di	=1N3924: 2500V	32a		—
1N3928	Si-Di	=1N3924: 3000V	32a		—
1N3929	Si-Di	Gl, 1000V, 1A	34a	USA	BY127, BY133, BY227, 1N4007, ++
1N393	Z-Di	=1N379: 120V	31a		—
1N3830	Si-Di	=1N3929: 1500V	34a		BY269, DM513, EM518, GP10W
1N3931	Si-Di	=1N3929: 2000V	34a		—
1N3932	Si-Di	=1N3929: 2500V	34a		—
1N3933	Si-Di	=1N3929: 3000V	34a		—
1N3934	Si-Di	Gl-L, 1200V, 10A	32a	USA	BYX42/1200, BYX98/1200
1N3935	Trigger-Di	Ub=26..34V, Ib<15μA, Itsm=10A	31a	Spe	—
1N3936	Trigger-Di	Ub=18..24V, Ib<0,125mA, Itsm=10A	31a	Spe	—
1N3937	Trigger-Di	Ub=90..C3944110V, Ib<0,125mA, Itsm=10A	31a	Itt	—
1N3938	Si-Di	Gl, contr.av., 200V, 2A	34a	USA,Tho	BYW52..56, 1N5060..82
1N3939	Si-Di	=1N3938: 400V	34a		BYW53..56, 1N5060..62

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1N394	Z-Di	=1N379: 150V	31a		—
1N3940	Si-Di	=1N3938: 600V	34a		BYW54..56, 1N5061..62
1N3941	Si-Di	=1N3938: 600V	34a		BYW55..56, 1N5062
1N3942	Si-Di	=1N3938: 1000V	34a		BYW56
1N3943	Z-Di	2,5V, 0,75W	34a	Sol	—
1N3944	Ge-Di	S, 15V, <12ns	31a	USA	AAY48, 1N995
1N3945	Si-Di	VHF-Tuning	31a	Gen, Trw	—
1N3946	Si-Di	VHF-Tuning	31a	Gen, Trw	—
1N3947	Si-Di	VHF-Tuning	31a	Gen, Trw	—
1N3948	Si-Di	Tunnel-Di			—
1N3949	Z-Di	20V, 5%, 10W	32a	USA, Sie	BZX98/C20, BZY93/C20, ZX20, 1N2984, ++
1N395	Z-Di	=1N379: 180V	31a		—
1N3950	Z-Di	20V, 5%, 1,5W	2c	USA	—
1N3951	Z-Di	25V, 5%, 1,5W	2c	USA	—
1N3952	Si-Di	Gl, 130V, 0,2A	31a	Sem	BA189..190, BAY20..21, BAY45..46, ++
1N3953	Ge-Di	S, 40V, <300ns	31a	Idc, Sem	AAY28, 1N631, 1N633
1N3954	Si-Di	SS, 50V, <4ns	31a	Idc, Msc, Sem	BAW62, BAX95, 1N4146..49, 1N4446..49++
1N3955	Si-Di	Gl-L, 100V, 70A(Tc=150°)	32	old	—
1N3956	Si-Di	SS, 30V, 2ns	31a	Idc, Sem	BA218, BAX13, BAX91, 1N4148..49, ++
1N3957(GP)	Si-Di	=1N3611: 1000V	31a	USA, Sie	BY127, BY133, BY227, 1N4007, ++
1N3956(C)	Si-Di	Gl/S-L, 100V, 3,5A	32a	USA	BYX38/300, BYX39/600
1N3959(C)	Si-Di	=1N3956: 200V	32a		BYX38/300, BYX39/600
1N396	Z-Di	=1N379: 220V	31a		—
1N3960(C)	Si-Di	=1N3956: 300V	32a		BYX38/300, BYX39/600
1N3961(C)	Si-Di	=1N3958: 400V	32a		BYX39/600, BYX39/600
1N3962(C)	Si-Di	=1N3956: 500V	32a		BYX38/600, BYX39/600
1N3963(C)	Si-Di	=1N3958: 600V	32a		BYX38/600, BYX39/600
1N3964	Si-Di	Gl-L, contr. av., 200V, 22A(Tc=120°)	32a	USA	BYX25/600
1N3965	Si-Di	=1N3964: 400V	32a		BYX25/600
1N3966	Si-Di	=1N3964: 600V	32a		BYX25/600
1N3967	Si-Di	=1N3964: 600V	32a		BYX25/600
1N3966	Si-Di	Gl-L, contr.av., 200V, 50A(Tc=120°)	32a	USA	—
1N3969	Si-Di	=1N3966: 400V	32a		—
1N397	Z-Di	=1N379: 270V	31a		—
1N3970	Si-Di	=1N3966: 600V	32a		—
1N3971	Si-Di	=1N3966: 600V	32a		—
1N3972	Si-Di	Gl-L, contr. av., 200V, 104A(Tc=120°)	73a	USA	—
1N3973	Si-Di	=1N3972: 400V	73a		—
1N3974	Si-Di	=1N3972: 600V	73a		—
1N3975	Si-Di	=1N3972: 600V	73a		—
1N3976	Si-Di	Gl-L, contr. av., 200V, 250A(Tc=120°)	73a	USA	—
1N3977	Si-Di	=1N3976: 400V	73a		—
1N3978	Si-Di	=1N3976: 600V	73a		—
1N3979	Si-Di	=1N3976: 600V	73a		—
1N396	Z-Di	=1N379: 330V	31a		—
1N3961	Si-Di	Gl, Uni, 200V, 3A	31a	USA	BY251..255, BYW17/200, 1N5402..06, ++
1N3982	Si-Di	=1N3981: 400V	31a		BY252..255, BYW17/400, 1N5404..08, ++
1N3963	Si-Di	=1N3931: 600V	31a		BY253..255, BYW17/400, 1N5406..06, ++
1N3964	Z-Di	5,5V, 5%, 10W	32a	USA, Sie	BZX98/C5V6, BZY93/C5V6, ZX5,8, 1N3997, ++
1N3965	Z-Di	=1N3984: 6V	32a		BZX98/C6V2, BZY93/C6V2, ZX6,2, 1N3998, ++
1N3966	Z-Di	=1N3984: 6,2V	32a		BZX98/C6V2, BZY93/C6V2, ZX6,2, 1N3998, ++
1N3967	Si-Di	Gl-L, 700V, 6A(Tc=150°)	32a	USA, Tho	BYX38/900, BYX39/800
1N3967R...3990R	Si-Di	=1N3967..3990:	32b		BYX38/..R, BYX39/..R
1N3966	Si-Di	=1N3967: 800V	32a		BYX38/900, BYX39/8+F407400
1N3969	Si-Di	=1N3987: 900V	32a		BYX38/900, BYX39/1000
1N399	Z-Di	=1N379: 390V	31a		—
1N3990	Si-Di	=1N3967: 1000V	32a		BYX38/1200, BYX39/1000
1N3991	Ge-Di	Uni, 35V	31a	Idc, Sem	AA117..116, AA132..134, 1N34, 1N54, ++
1N3992	Si-Di	kV-Gl, 4kV	31a	Edl, Sem	GP02-40, MR250-4, 1N1734A
1N3993	Z-Di	3,9V, 10%, 10W(Tc=55°)	32a	USA, Mot, Sie	BZX98/.., BZY93/.., ZL.., ZX
1N3993A...4000A	Z-Di	=1N3993..4000: 5%	32a		—
1N3994	Z-Di	=1N3993: 4,3V	32a		—
1N3995	Z-Di	=1N3993: 4,7V	32a		—
1N3996	Z-Di	=1N3993: 5,1V	32a		—
1N3997	Z-Di	=1N3993: 5,6V	32a		—
1N3998	Z-Di	=1N3993: 6,2V	32a		—

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1N3999	Z-Di	=1N3993: 6,8V	32a		—
1N40	Ge-Di	4xHF-Dem, gep, 25V, 225mA	4x31	Kem,Spe	—
1N400	Z-Di	=1N379: 470V	31a		—
1N4000	Z-Di	=1N3993: 7,5V	32a		—
1N4001(D,G,K,P,S)	Si-Di	Gl, Uni, 50V, 1A	31a	USA,EUR,JAP	BY126..127, BY133..135, 1N5614..22,++
1N4002(D,G,P,S)	Si-Di	=1N4001: 100V	31a		BY126..127, BY133..135, 1N5614..22,++
1N4003(D,G,P,S)	Si-Di	=1N4001: 200V	31a		BY126..127, BY133..134, 1N5614..22,++
1N4004(D,G,P,S)	Si-Di	=1N4001: 400V	31a		BY126..127, BY133..134, 1N5616..22,++
1N4005(D,G,P,S)	Si-Di	=1N4001: 600V	31a		BY126..127, BY133..134, 1N5618..22,++
1N4006(D,G,P,S)	Si-Di	=1N4001: 600V	31a		BY127, BY133, BY227, 1N5620..22,++
1N4007(D,G,P,S)	Si-Di	=1N4001: 1000V	31a		BY127, BY133, BY227, 1N5622,++
1N4007KH	Si-Di	=1N4001: 1600V	31a		DM513, DM516, EM516, GP10Y
1N4007KS	Si-Di	=1N4001: 1250V	31a		BY133, BYX95, EM513, GP10V,++
1N4008	Ge-Di	S, 12V, 0,1A, <70ns	31a	USA	AAZ18
1N4009	Si-Di	SS, 35V, 0,1A, <4ns	31a	USA,Phi,Tho	BA318, BAY38, BAX80, 1N4148..49,++
1N401	Si-St	1,5V	2c	Syl	—
1N4010	Ref-Di	6,2V, 5%, 0,4W	31a	USA,Sie	BZV10, BZV27, BZX90, 1N4560
1N4011	Si-Di	Gl, 1000V, 0,5A	34a	Sem,Ssi	BA159, BY127, BY133, 1N4007,++
1N4012	Si-Di	Gl-L, 700V, 12A(Tc=150°)	32a	USA	BYW88/800, BYX80..81, 1N4509..11,++
1N4013	Si-Di	=1N4012: 800V	32a		BYW88/800, BYX80..81, 1N4509..11,++
1N4014	Si-Di	=1N4012: 900V	32a		BYW88/1000, BYX81, 1N4510..11,++
1N4015	Si-Di	=1N4012: 1000V	32a		BYW88/1000, BYX81, 1N4510..11,++
1N4016	Z-Di	8,2V, 20%, 5W	≈32	USA	(BZX98/.., BZY93/.., ZX.., 1N2972..3005)
1N4016A...4042A	Z-Di	=1N4016..4042: 10%	≈32		—
1N4016B...4042B	Z-Di	=1N4016..4042: 5%	≈32		—
1N4017	Z-Di	=1N4016: 9,1V	≈32		—
1N4018	Z-Di	=1N4016: 10V	≈32		—
1N4019	Z-Di	=1N4016: 11V	≈32		—
1N402	Si-St	2V	2c		—
1N4020	Z-Di	=1N4016: 12V	≈32		—
1N4021	Z-Di	=1N4016: 13V	≈32		—
1N4022	Z-Di	=1N4016: 15V	≈32		—
1N4023	Z-Di	=1N4016: 16V	≈32		—
1N4024	Z-Di	=1N4016: 18V	≈32		—
1N4025	Z-Di	=1N4016: 20V	≈32		—
1N4026	Z-Di	=1N4016: 22V	≈32		—
1N4027	Z-Di	=1N4016: 24V	≈32		—
1N4026	Z-Di	=1N4016: 27V	≈32		—
1N4029	Z-Di	=1N4016: 30V	≈32		—
1N403	Si-St	2,5V	2c		—
1N4030	Z-Di	=1N4016: 33V	≈32		—
1N4031	Z-Di	=1N4016: 38V	≈32		—
1N4032	Z-Di	=1N4016: 39V	≈32		—
1N4033	Z-Di	=1N4016: 43V	≈32		—
1N4034	Z-Di	=1N4016: 47V	≈32		—
1N4035	Z-Di	=1N4016: 51V	≈32		—
1N4036	Z-Di	=1N4016: 56V	≈32		—
1N4037	Z-Di	=1N4016: 62V	≈32		—
1N4038	Z-Di	=1N4016: 68V	≈32		—
1N4039	Z-Di	=1N4016: 75V	≈32		—
1N404	Si-St	3,1V	2c		—
1N4040	Z-Di	=1N4016: 82V	≈32		—
1N4041	Z-Di	=1N4016: 91V	≈32		—
1N4042	Z-Di	=1N4016: 100V	≈32		—
1N4043	Si-Di	Min, SS, 25V, <4ns	≈31a	Idc	(BA218, BAX13, BAX91, 1N4148..49,++)
1N4044	Si-Di	Gl-L, 50V, 275A(Tc=120°)	73a	USA	—
1N4044R..4056R	Si-Di	=1N4044..4056:	73b		—
1N4045	Si-Di	=1N4044: 100V	73a		—
1N4046	Si-Di	=1N4044: 150V	73a		—
1N4047	Si-Di	=1N4044: 200V	73a		—
1N4048	Si-Di	=1N4044: 250V	73a		—
1N4049	Si-Di	=1N4044: 300V	73a		—
1N405	Si-St	3,7V	2c		—
1N4050	Si-Di	=1N4044: 400V	73a		—
1N4051	Si-Di	=1N4044: 500V	73a		—
1N4052	Si-Di	=1N4044: 600V	73a		—

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1N4053	Si-Di	=1N4044:700V	73a		—
1N4054	Si-Di	=1N4044:800V	73a		—
1N4055	Si-Di	=1N4044:900V	73a		—
1N4056	Si-Di	=1N4044:1000V	73a		—
1N4057(A)	Ref-Di	12,4V,5%,1,5W	31a	USA,Mot,Sie	—
1N4058(A)	Ref-Di	=1N4057:14,6V	31a		—
1N4059(A)	Ref-Di	=1N4057:16,8V	31a		—
1N406	Si-St	4,3V	2c		—
1N4060(A)	Ref-Di	=1N4057:18,5V	31a		—
1N4061(A)	Ref-Di	=1N4057:21V	31a		—
1N4062(A)	Ref-Di	=1N4057:23V	31a		—
1N4063(A)	Ref-Di	=1N4057:27V	31a		—
1N4064(A)	Ref-Di	=1N4057:30V	31a		—
1N4065(A)	Ref-Di	=1N4057:33V	31a		—
1N4066(A)	Ref-Di	=1N4057:37V	31a		—
1N4067(A)	Ref-Di	=1N4057:43V	31a		—
1N4068(A)	Ref-Di	=1N4057:47V	31a		—
1N4069(A)	Ref-Di	51V,5%,2W	31a		—
1N407	Si-St	5,2V	2c		—
1N4070(A)	Ref-Di	=1N4069:56V	31a		—
1N4071(A)	Ref-Di	=1N4069:62V	31a		—
1N4072(A)	Ref-Di	=1N4069:68V	31a		—
1N4073(A)	Ref-Di	=1N4069:75V	31a		—
1N4074(A)	Ref-Di	=1N4069:62V	31a		—
1N4075(A)	Ref-Di	=1N4069:87V	31a		—
1N4076(A)	Ref-Di	=1N4069:91V	31a		—
1N4077(A)	Ref-Di	=1N4069:100V	31a		—
1N4078(A)	Ref-Di	=1N4069:105V	31a		—
1N4079(A)	Ref-Di	=1N4069:110V	31a		—
1N406	Si-St	6,2V	2c		—
1N4060(A)	Ref-Di	=1N4069:120V	31a		—
1N4061(A)	Ref-Di	130V,5%,2,5W	31a		—
1N4082(A)	Ref-Di	=1N4061:140V	31a		—
1N4083(A)	Ref-Di	=1N4081:150V	31a		—
1N4084(A)	Ref-Di	=1N4081:175V	31a		—
1N4065(A)	Ref-Di	=1N4081:200V	31a		—
1N4088	Si-Di	S,70V,<200ns	31a	USA	BAW49..50, BAX15..17, BAY72,++
1N4087	Si-Di	SS,50V,<2,5ns	31a	USA	BA318, BAY38, BAY95, 1N4148..49,++
1N4068	Ge-Di	Uni,30V	31a	USA	AA117..118, AA132..14, 1N34, 1N54,++
1N4089	Si-Di	GI,400V,1,1A	31a	USA	BY126..127, BY133..134, 1N4004..07,++
1N409	Si-St		2c		—
1N4090	Ge-Di	Tunnel-Di	34a	Gen	—
1N4091	Si-Di	UHF-Tuning	Koax	Miv	—
1N4092	Si-Di	Uni,50V	31a	USA	BA127, BA187..190, 1N4148..49,++
1N4093	Si-Di	Uni,50V	31a	USA	BA127, BA187..190, 1N4148..49.++
1N4094	Z-Di	9,4V,2%,1W		Gsi	—
1N4095	Z-Di	5V,10%,0,33W	31a	USA,Sie	BZX55/C5V1.BZX79/C5V1,ZPD5,1,1N5231 ++
1N4096	Z-Di	90V,5%,3W	31a	USA	BZT03/..
1N4097	Z-Di	=1N4096:100V	31a		—
1N4096	Z-Di	=1N4096:150V	31a		—
1N4099	Z-Di	6,8V,5%,0,4W,re	31a	USA,Sie,Tho	BZV39/..
1N41	Ge-Di	4xHF-Dem,gep,32V		Kem,Spe	—
1N410	Si-Di			Syl	—
1N4100	Z-Di	=1N4099:7,5V	31a		—
1N4101	Z-Di	=1N4099:8,2V	31a		—
1N4102	Z-Di	=1N4099:8,7V	31a		—
1N4103	Z-Di	=1N4099:9,1V	31a		—
1N4104	Z-Di	=1N4099:10V	31a		—
1N4105	Z-Di	=1N4099:11V	31a		—
1N4106	Z-Di	=1N4099:12V	31a		—
1N4107	Z-Di	=1N4099:13V	31a		—
1N4108	Z-Di	=1N4099:14V	31a		—
1N4109	Z-Di	=1N4099:15V	31a		—
1N411(A,B)	Si-Di	GI-L,50V,25..50A	≈32/a	USA	BYX56/600, BYX97/300
1N4110	Z-Di	=1N4099:16V	31a		—
1N4111	Z-Di	=1N4099:17V	31a		—

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1N4112	Z-Di	=1N4099: 18V	31a		—
1N4113	Z-Di	=1N4099: 19V	31a		—
1N4114	Z-Di	=1N4099: 20V	31a		—
1N4115	Z-Di	=1N4099: 22V	31a		—
1N4116	Z-Di	=1N4099: 24V	31a		—
1N4117	Z-Di	=1N4099: 25V	31a		—
1N4118	Z-Di	=1N4099: 27V	31a		—
1N4119	Z-Di	=1N4099: 28V	31a		—
1N412(A,B)	Si-Di	=1N411(A,B):C4318 100V			BYX56/600, BYX97/300
1N4120	Z-Di	=1N4099: 30V	31a		—
1N4121	Z-Di	=1N4099: 33V	31a		—
1N4122	Z-Di	=1N4099: 36V	31a		—
1N4123	Z-Di	=1N4099: 39V	31a		—
1N4124	Z-Di	=1N4099: 43V	31a		—
1N4125	Z-Di	=1N4099: 47V	31a		—
1N4128	Z-Di	=1N4099: 51V	31a		—
1N4127	Z-Di	=1N4099: 56V	31a		—
1N4128	Z-Di	=1N4099: 60V	31a		—
1N4129	Z-Di	=1N4099: 62V	31a		—
1N413(A,B)	Si-Di	=1N411(AB): 200V			BYX56/600, BYX97/300
1N4130	Z-Di	=1N4099: 86V	31a		—
1N4131	Z-Di	=1N4099: 75V	31a		—
1N4132	Z-Di	=1N4099: 62V	31a		—
1N4133	Z-Di	=1N4099: 87V	31a		—
1N4134	Z-Di	=1N4099: 91V	31a		—
1N4135	Z-Di	=1N4099: 100V	31a		—
1N4136	Si-Di	GI-L, 200V, 70A(Tc=100°)	32a	USA	—
1N4137	Si-Di	=1N4136: 400V	32a		—
1N4136	Si-Di	=1N4136: 600V	32a		—
1N4139	Si-Di	GI, 50V, 3A	31a	USA	BY251..255, BYW17/100, 1N5400..08, ++
1N4140	Si-Di	=1N4139: 100V	31a		BY251..255, BYW17/100, 1N5401..08, ++
1N4141	Si-Di	=1N4139: 200V	31a		BY251..255, BYW17/200, 1N5402..08, ++
1N4142	Si-Di	=1N4139: 400V	31a		BY252..255, BYW17/400, 1N5404..08, ++
1N4143	Si-Di	=1N4139: 600V	31a		BY253..255, BYW17/600, 1N5406..08, ++
1N4144	Si-Di	=1N4139: 800V	31a		BY254..255, BYW17/800, 1N5407..08, ++
1N4145	Si-Di	=1N4139: 1000V	31a		BY255, BYW17/1000, 1N5408, ++
1N4146	Si-Di	=1N4139: 1200V	31a		BY255, BY228, BYW17/1200
1N4147	Si-Di	S, 30V, 10ns	31a	USA	BA218, BAX13, BAX91, 1N4148..49, ++
1N4148	Si-Di	SS, 100V, 0,2A, <4ns	31a	USA,EUR,JAP	BAW62, BAW76, BAX95, 1N4446..49, ++
1N4149	Si-Di	SS, 100V, 0,2A, <4ns	31a		BAW62, BAW76, BAX95, 1N4446..49, ++
1N415(A...H)	Si-Di	UHF, X-Band-M	Koax	USA	—
1N4150	Si-Di	SS, 50V, 0,2A, <4ns	31a	USA,EUR,TAP	BAW62, BAW78, BAX95, 1N4148..49, ++
1N4151	Si-Di	SS, 75V, 0,2A, <4ns	31a	USA,EUR,TAP	BAW62, BAW78, BAX95, 1N4146..49, ++
1N4152	Si-Di	SS, 40V, 0,2A, <4ns	31a	USA,EUR,JAP	BAW62, BAW76, BAX95, 1N4148..49, ++
1N4153	Si-Di	SS, 75V, 0,2A, <4ns	31a		BAW62, BAW78, BAX95, 1N4148..49, ++
1N4154	Si-Di	SS, 35V, 0,2A, <4ns	31a	USA,EUR,JAP	BAW62, BAW78, BAX95, 1N4148..49, ++
1N4155	Si-Di	S, Uni, 400V, 0,2A, <10µs	31a	USA	BA157..159, BA199/450, BAY89, ++
1N4156	Si-St	1,41V(1mA), 0,4W	31a	USA,Gen	BZ102/1V4, BZX75/C1V4, ZTE1,5
1N4157	Si-St	2,05V(1mA), 0,4W	31a		BZ102/2V1, BZX75/C2V1, ZTE1
1N4156	Z-Di	6,8V, 20%, 1W	31a	USA,Far,Tho	BZW22/.., BZX61/.., ZPY.., 1N5921..56, ++
1N4158A...4193A	Z-Di	=1N4158..4193: 10%	31a		—
1N4158B...4193B	Z-Di	=1N4158..4193: 5%	31a		—
1N4159	Z-Di	=1N4156: 7,5V	31a		—
1N416(A...G)	Si-Di	UHF, S-Band-M	Koax	USA	—
1N4160	Z-Di	=1N4158: 6,2V	31a		—
1N4161	Z-Di	=1N4158: 9,1V	31a		—
1N4162	Z-Di	=1N4158: 10V	31a		—
1N4163	Z-Di	=1N4158: 11V	31a		—
1N4164	Z-Di	=1N4156: 12V	31a		—
1N4165	Z-Di	=1N4158: 13V	31a		—
1N4166	Z-Di	=1N4156: 15V	31a		—
1N4187	Z-Di	=1N4156: 16V	31a		—
1N4188	Z-Di	=1N4156: 18V	31a		—
1N4169	Z-Di	=1N4156: 20V	31a		—
1N417	Ge-Di	S, 60V, 60mA, <300ns	31a	USA	AAZ15, AAZ17, 1N276
1N4170	Z-Di	=1N4156: 22V	31a		—

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1N4171	Z-Di	=1N4158: 24V	31a		—	
1N4172	Z-Di	=1N4158: 27V	31a		—	
1N4173	Z-Di	=1N4158: 30V	31a		—	
1N4174	Z-Di	=1N4158: 33V	31a		—	
1N4175	Z-Di	=1N4158: 36V	31a		—	
1N4176	Z-Di	=1N4158: 39V	31a		—	
1N4177	Z-Di	=1N4158: 43V	31a		—	
1N4178	Z-Di	=1N4158: 47V	31a		—	
1N4179	Z-Di	=1N4158: 51V	31a		—	
1N418	Ge-Di	S, 60V, 16mA, <300ns	31a	USA	AAY28, 1N191..192	
1N4180	Z-Di	=1N4158: 56V	31a		—	
1N4181	Z-Di	=1N4158: 62V	31a		—	
1N4182	Z-Di	=1N4158: 68V	31a		—	
1N4183	Z-Di	=1N4158: 75V	31a		—	
1N4184	Z-Di	=1N4158: 82V	31a		—	
1N4185	Z-Di	=1N4158: 91V	31a		—	
1N4186	Z-Di	=1N4158: 100V	31a		—	
1N4187	Z-Di	=1N4158: 110V	31a		—	
1N4188	Z-Di	=1N4158: 120V	31a		—	
1N4189	Z-Di	=1N4158: 130V	31a		—	
1N419	Ge-Di	S, 80V, 60mA, <300ns	31a	USA	AAZ15	
1N4190	Z-Di	=1N4158: 150V	31a		—	
1N4191	Z-Di	=1N4158: 160V	31a		—	
1N4192	Z-Di	=1N4158: 180V	31a		—	
1N4193	Z-Di	=1N4158: 200V	31a		—	
1N4194	Z-Di	6,8V, 20%, 10W	32a	Nae	BZX98/.., BZY93/.., ZX.., 1N2970..3015	
1N4194A...4239A	Z-Di	=1N4194..4239: 10%	32a		—	
1N4194B...4239B	Z-Di	=1N4194..4239: 5%	32a		—	
1N4195	Z-Di	=1N4194: 7,5V	32a		—	
1N4196	Z-Di	=1N4194: 8,2V	32a		—	
1N4197	Z-Di	=1N4194: 9,1V	32a		—	
1N4198	Z-Di	=1N4194: 10V	32a		—	
1N4199	Z-Di	=1N4194: 11V	32a		—	
1N42	Ge-Di	4xUni, 115V, 0,1A(ss)	4x31a	Kem,Spe	AA117..118, AA132..133	
1N4200	Z-Di	=1N4194: 12V	32a		—	
1N4201	Z-Di	=1N4194: 13V	32a		—	
1N4202	Z-Di	=1N4194: 14V	32a		—	
1N4203	Z-Di	=1N4194: 15V	32a		—	
1N4204	Z-Di	=1N4194: 16V	32a		—	
1N4205	Z-Di	=1N4194: 17V	32a		—	
1N4206	Z-Di	=1N4194: 18V	32a		—	
1N4207	Z-Di	=1N4194: 19V	32a		—	
1N4208	Z-Di	=1N4194: 20V	32a		—	
1N4209	Z-Di	=1N4194: 22V	32a		—	
1N4210	Z-Di	=1N4194: 24V	32a		—	
1N4211	Z-Di	=1N4194: 25V	32a		—	
1N4212	Z-Di	=1N4194: 27V	32a		—	
1N4213	Z-Di	=1N4194: 30V	32a		—	
1N4214	Z-Di	=1N4194: 33V	32a		—	
1N4215	Z-Di	=1N4194: 36V	32a		—	
1N4216	Z-Di	=1N4194: 39V	32a		—	
1N4217	Z-Di	=1N4194: 43V	32a		—	
1N4218	Z-Di	=1N4194: 45V	32a		—	
1N4219	Z-Di	=1N4194: 47V	32a		—	
1N4220	Z-Di	=1N4194: 50V	32a		—	
1N4221	Z-Di	=1N4194: 51V	32a		—	
1N4222	Z-Di	=1N4194: 52V	32a		—	
1N4223	Z-Di	=1N4194: 58V	32a		—	
1N4224	Z-Di	=1N4194: 62V	32a		—	
1N4225	Z-Di	=1N4194: 68V	32a		—	
1N4226	Z-Di	=1N4194: 75V	32a		—	
1N4227	Z-Di	=1N4194: 82V	32a		—	
1N4228	Z-Di	=1N4194: 91V	32a		—	
1N4229	Z-Di	=1N4194: 100V	32a		—	
1N4230	Z-Di	=1N4194: 105V	32a		—	
1N4231	Z-Di	=1N4194: 110V	32a		—	

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1N4232	Z-Di	=1N4194: 120V	32a		—
1N4233	Z-Di	=1N4194: 130V	32a		—
1N4234	Z-Di	=1N4194: 140V	32a		—
1N4235	Z-Di	=1N4194: 150V	32a		—
1N4236	Z-Di	=1N4194: 160V	32a		—
1N4237	Z-Di	=1N4194: 175V	32a		—
1N4238	Z-Di	=1N4194: 160V	32a		—
1N4239	Z-Di	=1N4194: 200V	32a		—
1N4240	Z-Di	5V, 2%, 10W	32	Idc, Sie	BZX98/5V1, BZY93/C5V1, ZX5,1
1N4241	Z-Di	6V, 2%, 10W	32	Idc, Sie	BZX98/C6V2, BZY93/C6V2, ZX6,2
1N4242	Si-Di	2xSS, 40V, <2ns	42	USA	—
1N4243	Si-Di	4xSS, 40V, <2ns		USA	—
1N4244	Si-Di	SS, 10V, 0,05A, <0,75ns	31a	USA, Tho	BAY62, 1N4376
1N4245(GP)	Si-Di	Gl, Uni, 200V, 1A	31a	USA, Sie	BY126..127, BY133..134, 1N4003..07,++
1N4246(GP)	Si-Di	=1N4245: 400V	31a		BY126..127, BY133..134, 1N4004..07,++
1N4247(GP)	Si-Di	=1N4245: 600V	31a		BY126..127, BY133..134, 1N4005..07,++
1N4248(GP)	Si-Di	=1N4245: 600V	31a		BY127, BY133, BY227, 1N4006..07,++
1N4249(GP)	Si-Di	=1N4245: 1000V	31a		BY127, BY133, BY227, 1N4007,++
1N424A	Si-Di	Uni, 150V, 0,225A(ss)	31a	Tho	BA147/150, BA190, 1N5195..96,++
1N4250	Si-Di	Gl, 800V, 0,5A	31a	USA	BY127, BY133, BY227, 1N4006..07,++
1N4251	Si-Di	=1N4250: 1000V	31a		BY127, BY133, BY227, 1N4007,++
1N4252	Si-Di	=1N4250: 1200V	31a		BY127, BY133, BY227, BY266, GP10Q++
1N4253	Si-Di	=1N4250: 1500V	31a		BY269, DM513, EM516, GP10W,++
1N4254	Si-Di	Gl, 1500V, 0,25A	31a	USA	BAY91, BY203/16, GP02-20, SHG1,5,++
1N4255	Si-Di	=1N4254: 2000V	31a		BAY91, BY203/20, GP02-20, SHG2,++
1N4256	Si-Di	=1N4254: 2500V	31a		GP02-30, MR250-3, SHG2,5
1N4257	Si-Di	=1N4254: 3000V	31a		GP02-30, MR250-3, SHG2,5
1N4258	Z-Di	6,6V, 20%, 10W	21	Nae	(BZX98/.., BZY93/.., ZX.., 1N2970..3015)
1N4258A...4293A	Z-Di	=1N4256...4293: 10%	21		—
1N4258B...4293B	Z-Di	=1N4256...4293: 5%	21		—
1N4259	Z-Di	=1N4256: 7,5V	21		—
1N4260	Z-Di	=1N4256: 6,2V	21		—
1N4261	Z-Di	=1N4256: 9,1V	21		—
1N4262	Z-Di	=1N4256: 10V	21		—
1N4263	Z-Di	=1N4256: 11V	21		—
1N4264	Z-Di	=1N4256: 12V	21		—
1N4265	Z-Di	=1N4258: 13V	21		—
1N4266	Z-Di	=1N4258: 15V	21		—
1N4267	Z-Di	=1N4258: 16V	21		—
1N4268	Z-Di	=1N4258: 16V	21		—
1N4269	Z-Di	=1N4256: 20V	21		—
1N4270	Z-Di	=1N4258: 22V	21		—
1N4271	Z-Di	=1N4258: 24V	21		—
1N4272	Z-Di	=1N4258: 27V	21		—
1N4273	Z-Di	=1N4256: 30V	21		—
1N4274	Z-Di	=1N4258: 33V	21		—
1N4275	Z-Di	=1N4256: 38V	21		—
1N4276	Z-Di	=1N4256: 39V	21		—
1N4277	Z-Di	=1N4258: 43V	21		—
1N4278	Z-Di	=1N4258: 47V	21		—
1N4279	Z-Di	=1N4258: 51V	21		—
1N4260	Z-Di	=1N4258: 56V	21		—
1N4261	Z-Di	=1N4258: 62V	21		—
1N4262	Z-Di	=1N4258: 66V	21		—
1N4283	Z-Di	=1N4258: 75V	21		—
1N4284	Z-Di	=1N4258: 62V	21		—
1N4285	Z-Di	=1N4258: 91V	21		—
1N4266	Z-Di	=1N4258: 100V	21		—
1N4287	Z-Di	=1N4256: 110V	21		—
1N4266	Z-Di	=1N4258: 120V	21		—
1N4289	Z-Di	=1N4258: 130V	21		—
1N429	Ref-Di	6,2V, 5%, 0,2W	2c	Inr, Mot,++	BZV10, BZV27, BZX90, 1N821, 1N4580,++
1N4290	Z-Di	=1N4258: 150V	21		—
1N4291	Z-Di	=1N4256: 160V	21		—
1N4292	Z-Di	=1N4256: 160V	21		—
1N4293	Z-Di	=1N4258: 200V	21		—

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1N4294	Si-Di	UHF,S-Band-M	Koax	USA	—
1N4295(A)	Ref-Di	10V,0,4W	31a	USA	—
1N4296(A)	Ref-Di	10V,1W	34a	USA	—
1N4297(A,B)	Ref-Di	8,8V,5%,10W	32	USA	—
1N4298(A,B)	Ref-Di	8,8V,5%,10W	32		—
1N4299(A,B)	Ref-Di	11,3V,5%,10W	32		—
1N43	Ge-Di	Uni,70V,40mA	31a	USA,Tho	AA117..118,AA132..134,1N34,1N54
1N430(A,B)	Ref-Di	8,4V,5%,0,25W		USA	—
1N4300(A,B)	Ref-Di	11,3V,5%,10W	32		—
1N4301(A,B)	Ref-Di	8,8V,5%,50W	32		—
1N4302(A,B)	Ref-Di	8,8V,5%,50W	32		—
1N4303(A,B)	Ref-Di	11,3V,5%,50W	32		—
1N4304(A,B)	Ref-Di	11,3V,5%,50W	32		—
1N4305	Si-Di	SS,75V,0,1A,<4ns	31a	USA,Hit,Tho	BAW62,BAW78,BAX95,1N4148..49,++
1N4306	Si-Di	2xSS,75V,0,2A,<4ns	42	USA	—
1N4307	Si-Di	4xSS,75V,0,2A,<4ns		USA	—
1N4308	Si-Di	SS,100V,<2ns	31a	USA,Tho	BAW62,BAW76,BAX95,1N4148..49,++
1N4308	Si-Di	SS,50V,<2ns	31a	USA,Tho	(BAW24..27)
1N431(B)	Si-Di	Uni,88..75V,10mA	2c	USA	BA147/100,BA188,1N5194..96,++
1N4310	Si-Di	SS,75V,<2ns	31a	USA,Tho	(BAW26..27)
1N4311	Si-Di	SS,100V,<2ns	31s	USA,Tho	(BAV14)
1N4312	Si-Di	SS,150V,<2ns	31a	USA,Tho	(BAV14)
1N4313	Si-Di	SS,100V,<2ns	31a	USA,Tho	BAW62,BAW76,BAX95,1N4148..49,++
1N4314	Si-Di	=1N4308:Min	31a		→1N4308
1N4315	Si-Di	=1N4309:Min	31a		→1N4309
1N4316	Si-Di	=1N4310:Min	31a		→1N4310
1N4317	Si-Di	=1N4311:Min	31a		→1N4311
1N4318	Si-Di	=1N4312:Min	31a		→1N4312
1N4319	Si-Di	=1N4313:Min	31a		→1N4313
1N432(A,B)	Si-Di	S,40V,55..85mA,3ns		USA	BA318,BAY38,BAX13,1N3062..64,++
1N4320	Si-Di			USA	—
1N4321	Z-Di	50V,10%,3W	31a	USA	BZT03/C51,BZV40/C51,BZ+F4370V48/C51
1N4322	Si-Di	SS,75V,<8ns	31a	USA	BAW62,BAW76,BAX95,1N4148..49,++
1N4323	Z-Di	8,8V,20%,1W	31a	USA	BZW22/..,BZX61/..,ZPY..,1N5921..56,++
1N4323A...4358A	Z-Di	=1N4323..4358:10%	31a		—
1N4323B...4356B	Z-Di	=1N4323..4358:5%	31a		—
1N4324	Z-Di	=1N4323:7,5V	31a		—
1N4325	Z-Di	=1N4323:8,2V	31a		—
1N4326	Z-Di	=1N4323:9,1V	31a		—
1N4327	Z-Di	=1N4323:10V	31a		—
1N4328	Z-Di	=1N4323:11V	31a		—
1N4329	Z-Di	=1N4323:12V	31a		—
1N433(A,B)	Si-Di	S,145V,40..60mA,3ns		USA	BA203
1N4330	Z-Di	=1N4323:13V	31a		—
1N4331	Z-Di	=1N4323:15V	31a		—
1N4332	Z-Di	=1N4323:16V	31a		—
1N4333	Z-Di	=1N4323:18V	31a		—
1N4334	Z-Di	=1N4323:20V	31a		—
1N4335	Z-Di	=1N4323:22V	31a		—
1N4335	Z-Di	=1N4323:24V	31a		—
1N4337	Z-Di	=1N4323:27V	31a		—
1N4338	Z-Di	=1N4323:30V	31a		—
1N4339	Z-Di	=1N4323:33V	31a		—
1N434(A,B)	Si-Di	S,180V,35..60mA,3ns		USA	—
1N4340	Z-Di	=1N4323:38V	31a		—
1N4341	Z-Di	=1N4323:39V	31a		—
1N4342	Z-Di	=1N4323:43V	31a		—
1N4343	Z-Di	=1N4323:47V	31a		—
1N4344	Z-Di	=1N4323:51V	31a		—
1N4345	Z-Di	=1N4323:56V	31a		—
1N4346	Z-Di	=1N4323:62V	31a		—
1N4347	Z-Di	=1N4323:88V	31a		—
1N4348	Z-Di	=1N4323:75V	31a		—
1N4349	Z-Di	=1N4323:62V	31a		—
1N435	Ge-Di	4xUni,40V,80mA		Spe	—
1N4350	Z-Di	=1N4323:91V	31a		—

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1N4351	Z-Di	=1N4323: 100V	31a		—
1N4352	Z-Di	=1N4323: 110V	31a		—
1N4353	Z-Di	=1N4323: 120V	31a		—
1N4354	Z-Di	=1N4323: 130V	31a		—
1N4355	Z-Di	=1N4323: 150V	31a		—
1N4356	Z-Di	=1N4323: 160V	31a		—
1N4357	Z-Di	=1N4323: 180V	31a		—
1N4358	Z-Di	=1N4323: 200V	31a		—
1N4359	Si-Di	Rauschdiode, white noise diode, 200V	31a	Sol	—
1N436	Ref-Di	4V		Ray	—
1N4360	Z-Di	2,4V, 5%, 0,25W	31a	USA,Sie	BZX55/C2V4, BZX79/C2V4, 1N5221,++
1N4361	Si-Di	Gl, 900V, 0,5A	31a	USA	BY127, BY133, BY227, 1N4007,++
1N4362	Si-St	0,65V(1mA), 0,4W	31a	USA	BZ102/0V7, BZX55/C0V8, ZPD1
1N4363	Si-Di	S, 120V, 0,1A, <40ns	31a	USA	BA197..198, BAV19..21, 1N3070,++
1N4364	Si-Di	Gl, 100V, 0,75A	34a	USA,Tix	BY126..127, BY133..135, 1N4002..07,++
1N4364R..4369R	Si-Di	=1N4364..4369:	34b		→1N4364..F45004369
1N4365	Si-Di	=1N4364: 200V	34a		BY126..127, BY133..134, 1N4003..07,++
1N4366	Si-Di	=1N4364: 300V	34a		BY126..127, BY133..134, 1N4004..07,++
1N4367	Si-Di	=1N4364: 400V	34a		BY126..127, BY133..134, 1N4004..07,++
1N4368	Si-Di	=1N4364: 500V	34a		BY126..127, BY133..134, 1N4005..07,++
1N4369	Si-Di	=1N4364: 600V	34a		BY126..127, BY133..134, 1N4005..07,++
1N437(A)	Ref-Di	5V		Ray	—
1N4370	Z-Di	2,4V, 10%, 0,4W	31a	USA,Sie,Tho	BZX55/.., BZX79/.., ZPD.., 1N5221..25
1N4370A..4372A	Z-Di	=1N4370..4372: 5%	31a		—
1N4371	Z-Di	=1N4370: 2,7V	31a		—
1N4372	Z-Di	=1N4370: 3V	31a		—
1N4373	Si-Di	SS, 60V, 4ns			BAW62, BAW76, BAX95, 1N4148..49,++
1N4374	Si-Di	Gl, 1500V, 0,75A	34a	Scn	BY269, BY350/1500, DM513, GP10W,++
1N4375	Si-Di	SS, 60V, <6ns	31a	Idc,Spe	BA218, BAX13, BAX91, 1N4148..49,++
1N4376	Si-Di	SS, 10V, 0,05A, <6ns	31a	USA	BAY82, 1N4244
1N4377	Si-Di	kV-Gl, 2,5kV, 0,75A		Scn,Sem	—
1N4376	Opto				—
1N4379	Si-Di	UHF, S-Band-Dem	31a	Miv,Sld	—
1N436(A)	Raf-Di	7V		Ray	—
1N4380	Si-Di	SS, 50V, 0,05A, <1,8ns	31a	USA	—
1N4361	Ge-Di	S, 25V, <100ns	31a	USA	AAY27, AAZ18, 1N3592
1N4382	Si-Di	SS, 55V, <5,5ns	31a	Msc	BAW76
1N4383(GP)	Si-Di	Gl, 200V, 1A	31a	USA,Gie,Tho	BY126..127, BY133..134, 1N4003..07,++
1N4384(GP)	Si-Di	=1N4363: 400V	31a		BY126..127, BY133..134, 1N4004..07,++
1N4365(GP)	Si-Di	=1N4383: 600V	31a		BY128..127, BY133..134, 1N4003..07,++
1N4386	Si-Di	UHF-Multipl, PQ>32,5W(150MHz)	32a	Pai	—
1N4387	Si-Di	UHF-Multipl, PQ>15W(450MHz)	32a	Mot,Pai	—
1N4366	Si-Di	UHF-Multipl, PQ>11W(1000MHz)	32a	Mot,Pai	—
1N4389	Si-Di	Uni, 5V	31a	Idc	—
1N439	Ref-Di	10V			—
1N4390	Si-Di	SS, 20V, <0,5ns	31a	USA	—
1N4391	Si-Di	SS, 20V, <0,5ns	31a	USA	—
1N4392	Si-Di	SS, 15V, <0,5ns	31a	USA	—
1N4393(A,B)	Si-Di	Tunnel-Di	34	Msc,Ssi	—
1N4394(A,B)	Si-Di	Tunnel-Di	34	Msc,Ssi	—
1N4395(AB)	Si-Di	Tunnel-Di	34	Msc,Ssi	—
1N4396(A,B)	Si-Di	Tunnel-Di	34	Msc,Ssi	—
1N4397(AB)	Si-Di	Tunnel-Di	34	Msc,Ssi	—
1N4398(AB)	Si-Di	Tunnel-Di	34	Msc,Ssi	—
1N4399(AB)	Si-Di	Tunnel-Di	34	Msc,Ssi	—
1N44	Ge-Di	Uni, 115V, 35mA	31a	USA	AA117..118, AA132..134, 1N34, 1N54
1N440(B)	Si-Di	Gl-L, 100V, 0,3..0,75A	34a	Rca,Tix,++	BY126..127, BY133..35, 1N4002..07,++
1N4400	Z-Di	6,8V, 20%, 1W	31a	USA	BZW22/.., BZX61/.., ZPY.., 1N5921..56,++
1N4400A..4435A	Z-Di	=1N4400..4435: 10%	31a		—
1N4400B..4435B	Z-Di	=1N4400..4435: 5%	31a		—
1N4401	Z-Di	=1N4400: 7,5V	31a		—
1N4402	Z-Di	=1N4400: 8,2V	31a		—
1N4403	Z-Di	=1N4400: 9,1V	31a		—
1N4404	Z-Di	=1N4400: 10V	31a		—
1N4405	Z-Di	=1N4400: 11V	31a		—
1N4406	Z-Di	=1N4400: 12V	31a		—

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1N4407	Z-Di	=1N4400: 13V	31a		—
1N4408	Z-Di	=1N4400: 15V	31a		—
1N4409	Z-Di	=1N4400: 16V	31a		—
1N441(B)	Si-Di	=1N440(B): 200V	34a		BY126..127, BY133..134, 1N4003..07,++
1N4410	Z-Di	=1N4400: 18V	31a		—
1N4411	Z-Di	=1N4400: 20V	31a		—
1N4412	Z-Di	=1N4400: 22V	31a		—
1N4413	Z-Di	=1N4400: 24V	31a		—
1N4414	Z-Di	=1N4400: 27V	31a		—
1N4415	Z-Di	=1N4400: 30V	31a		—
1N4416	Z-Di	=1N4400: 33V	31a		—
1N4417	Z-Di	=1N4400: 36V	31a		—
1N4418	Z-Di	=1N4400: 39V	31a		—
1N4419	Z-Di	=1N4400: 43V	31a		—
1N442(B)	Si-Di	=1N440(B): 300V	34a		BY126..127, BY133..134, 1N4004..07,++
1N4420	Z-Di	=1N4400: 47V	31a		—
1N4421	Z-Di	=1N4400: 51V	31a		—
1N4422	Z-Di	=1N4400: 56V	31a		—
1N4423	Z-Di	=1N4400: 62V	31a		—
1N4424	Z-Di	=1N4400: 68V	31a		—
1N4425	Z-Di	=1N4400: 75V	31a		—
1N4426	Z-Di	=1N4400: 82V	31a		—
1N4427	Z-Di	=1N4400: 91V	31a		—
1N4428	Z-Di	=1N4400: 100V	31a		—
1N4429	Z-Di	=1N4400: 110V	31a		—
1N443(B)	Si-Di	=1N440(B): 400V	34a		BY126..127, BY133..134, 1N4004..07,++
1N4430	Z-Di	=1N4400: 120V	31a		—
1N4431	Z-Di	=1N4400: 130V	31a		—
1N4432	Z-Di	=1N4400: 150V	31a		—
1N4433	Z-Di	=1N4400: 160V	31a		—
1N4434	Z-Di	=1N4400: 180V	31a		—
1N4435	Z-Di	=1N4400: 200V	31a		—
1N4436	Si-Di	GI-L, 200V, 10A		old	—
1N4437	Si-Di	=1N4436: 400V			—
1N4438	Si-Di	=1N4436: 600V			—
1N4439	Si-Di	=1N4436: 800V			—
1N444(B)	Si-Di	=1N440(B): 500V	34a		BY126..127, BY133..134, 1N4005..07,++
1N4440	Si-Di	=1N4436: 1000V			—
1N4441	Si-Di	GI, S, 1500V, 25mA, <300ns	31a	old	BY203/16, BY269, SHG1,5
1N4442	Si-Di	SS, 30V, 1ns	31a		BA218, BAX13, BAX91, 1N4148..49, ++
1N4443	Si-Di	SS, 30V, 0,6ns			BA218, BAX13, BAX91, 1N4148..49, ++
1N4444	Si-Di	SS, 70V, 0,225A, <7ns	31a	USA,Tix,Tho	BAW62, BAW76, BAX95, 1N4148..49, ++
1N4445	Si-Di	SS, 125V, <4ns	31a	USA,Tho	BA219, BAX96
1N4446	Si-Di	SS, 100V, 0,2A, <4ns	31a	USA,EUR	BAW62, BAX95, 1N4148..49, 1N4151, ++
1N4447	Si-Di	SS, 100V, 0,2A, <4ns	31a		BAW62, BAX95, 1N4148..49, 1N4151,++
1N4448	Si-Di	SS, 100V, 0,2A, <4ns	31a		BAW62, BAX95, 1N4148..49, 1N4151, ++
1N4449	Si-Di	SS, 100V, 0,2A, <4ns	31a		BAW62, BAX95, 1N4148..49, 1N4151,++
1N445(B)	Si-Di	=1N440(B): 600V	34a		BY126..127, BY133..134, 1N4005..07,++
1N4450	Si-Di	SS, 30V, 0,2A, <4ns	31a	USA,EUR,Hit	BA221, BAY74, 1N4148..49, 1N4154,++
1N4451	Si-Di	SS, 30V, 0,2A, <10ns	31a	USA,EUR	BA221, BAY74, 1N4148..49, 1N4154,++
1N4452	Si-Di	S, 40V, <20ns	31a	USA	BAV15..16, BAV44, BAW24..27
1N4453	Si-S1	0,8V(10mA), 0,5W	31a	USA	BA220, BZ102/0V7, BZX55/C0V8, ZPD1,++
1N4454	Si-Di	SS, 50V, 0,2A, <10ns	31a	USA,EUR,Hit	BAW62, BAX95, 1N4148..49, 1N4151, ++
1N4455	Si-Di	Uni, 50V	31a	Gen,Tix,Uni	BA128, BA147/50, BA222, 1N5194, ++
1N4456	Si-Di	SS, 35V, <1,5ns	31a	Idc,Sem	—
1N4457	Si-Di	SS, 50V, <1,5ns	31a	Idc,Sem	—
1N4458	Si-Di	GI-L, 800V, 5A(Tc=150°)	32a	USA	BYX38/900, BYX39/800
1N4458...4459R	Si-Di	=1N4458..4459:	32b		BYX38/..R, BYX39/..R
1N4459	Si-Di	=1N4458: 1000V	32a		BYX38/1200, BYX39/1000
1N446	Si-Di	UHF, K/Ka-Band-Dem	Koax	Syl	—
1N4460	Z-Di	6,2V, 5%, 1,5W	31a	USA	BZV47/.., BZY97/.., ZY.., 1N5920..58,++
1N4461	Z-Di	=1N4480: 6,8V	31a		—
1N4462	Z-Di	=1N4460: 7,5V	31a		—
1N4463	Z-Di	=1N4480: 8,2V	31a		—
1N4464	Z-Di	=1N4460: 9,1V	31a		—
1N4465	Z-Di	=1N4460: 10V	31a		—

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1N4466	Z-Di	=1N4460: 11V	31a		—
1N4467	Z-Di	=1N4460: 12V	31a		—
1N4468	Z-Di	=1N4460: 13V	31a		—
1N4469	Z-Di	=1N4460: 15V	31a		—
1N447	Ge-Di	Uni, 40V, 60mA	31a	USA	AA117..118, AA132..134, 1N34, 1N54,++
1N4470	Z-Di	=1N4460: 16V	31a		—
1N4471	Z-Di	=1N4460: 18V	31a		—
1N4472	Z-Di	=1N4460: 20V	31a		—
1N4473	Z-Di	=1N4460: 22V	31a		—
1N4474	Z-Di	=1N4460: 24V	31a		—
1N4475	Z-Di	=1N4480: 27V	31a		—
1N4476	Z-Di	=1N4460: 30V	31a		—
1N4477	Z-Di	=1N4460: 33V	31a		—
1N4478	Z-Di	=1N4460: 36V	31a		—
1N4479	Z-Di	=1N4480: 39V	31a		—
1N448	Ge-Di	Uni, 100V, 60mA	31a	USA	AA117..118, AA132..133
1N4460	Z-Di	=1N4460: 43V	31a		—
1N4481	Z-Di	=1N4460: 47V	31a		—
1N4482	Z-Di	=1N4460: 51V	31a		—
1N4483	Z-Di	=1N4460: 56V	31a		—
1N4484	Z-Di	=1N4460: 82V	31a		—
1N4485	Z-Di	=1N4460:C4578 68V	31a		—
1N4466	Z-Di	=1N4460: 75V	31a		—
1N4487	Z-Di	=1N4460: 82V	31a		—
1N4488	Z-Di	=1N4460: 91V	31a		—
1N4489	Z-Di	=1N4460: 100V	31a		—
1N449	Ge-Di	Uni, 40V, 60mA	31a	USA	AA117..118, AA132..134, 1N34, 1N54,++
1N4490	Z-Di	=1N4480: 110V	31a		—
1N4491	Z-Di	=1N4480: 120V	31a		—
1N4492	Z-Di	=1N4460: 130V	31a		—
1N4493	Z-Di	=1N4460: 150V	31a		—
1N4494	Z-Di	=1N4460: 160V	31a		—
1N4495	Z-Di	=1N4460: 180V	31a		—
1N4496	Z-Di	=1N4460: 200V	31a		—
1N4497	Si-Di	kV-Gl, 1,6kV, 0,75A		Sem,Ssi	—
1N4496	Si-Di	=1N4497: 3kV			—
1N4499	Z-Di	6,2V, 5%, 1W	31a	Idc,Sem	BZW22/C6V2, BZX61/C6V2, ZPY6,2, 1N5920++
1N44A1	Si-Di	kV-Gl, 13kV, 0,67A		Tos	—
1N45	Ge-Di	HF, Uni, 75V, 35mA	31a	USA	AA113, AA117..118, 1N34, 1N60
1N450	Ge-Di	Uni, 100V, 60mA	31a	USA	AA117..118, AA132..133
1N4500	Si-Di	SS, 80V, <4ns	31a	USA	BAW62, BAX95, 1N4148..49, 1N4151, ++
1N4501	Ref-Di	7V, 5%, 0,21W	31a	Idc,Msc	—
1N4502	Ge-Di	Uni, 20V	31a	Idc,Sem	AA117..119, AA132..134, 1N34, 1N54,++
1N4503	Z-Di	33V, 10%, 3W	31a	Msc,Trw	BZT03/C, D33
1N4504	Z-Di	200V, 10%, 3W	31a	Msc,Trw	BZT03/C, D200
1N4505	Si-Di	kV-Gl, 6kV, 0,1A	31a	USA	BYX90, 1N5183
1N4506	Si-Di	Gl, contr.av., 200V, 12A(Tc=135°)	32a	USA	BYX25/600
1N4507	Si-Di	=1N4506: 400V	32a		BYX25/600
1N4508	Si-Di	=1N4506: 600V	32a		BYX25/600
1N4509	Si-Di	=1N4506: 800V	32a		BYX25/600
1N451	Ge-Di	Uni, 175V, 60mA	31a	USA	1N39
1N4510	Si-Di	=1N4506: 1000V	32a		BYX25/1000
1N4511	Si-Di	=1N4506: 1200V	32a		BYX25/1200
1N4512	Si-Di	Uni, 10V	12a	Ssi	BA128, BA147/25, BA222, 1N5194, ++
1N4513	Si-Di	Gl, 2000V, 0,25A	31a	USA	BAY91, BY203/20, HVG2, SHG2, ++
1N4514	Si-Di	Gl, 800V, 1,1A	31a	USA	BY127, BY133, BY227, 1N4006..07,++
1N4517	Si-Di	Gl, 200V, 2A	31a	USA	BY251..255, BY259/300, 1N5060..82,++
1N452	Ge-Di	Uni, 35V	31a	USA	AA136
1N4523	Ge-Di	SS, 15V, <8ns	31a	USA	AAY21
1N4524	Ge-Di	SS, 10V, <3ns	31a	USA	1N995
1N4525	Si-Di	Gl-L, contr.av., 200V, 35A(Tc=115°)	32a	USA	BYX56/600
1N4526	Si-Di	=1N4525: 400V	32a		BYX56/600
1N4527	Si-Di	=1N4525: 600V	32a		BYX56/600
1N4528	Si-Di	=1N4525: 600V	32a		BYX56/600
1N4529	Si-Di	=1N4525: 1000V	32a		BYX56/1000
1N453	Ge-Di	Uni, 115V	31a	USA	1N270

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1N4530	Si-Di	=1N4525: 1200V	32a		BYX56/1200
1N4531	Si-Di	SS, 75V, 0,15A, <4ns	31a	USA, Phi, Tho	BAW62, BAX95, 1N4148..49, 1N4151, ++
1N4532	Si-Di	SS, 75V, 0,15A, <2ns	31a	USA, Phi, Tho	BAW62, BAX95, 1N4148..49, 1N4151, ++
1N4533	Si-Di	SS, 40V, 0,075A, <2ns	31a	USA, Phi, Tho	BAW62, BAX95, 1N4148..49, 1N4151, ++
1N4534	Si-Di	SS, 75V, 0,075A, <2ns	31a	USA, Phi, Tho	BAW62, BAX95, 1N4148..49, 1N4151, ++
1N4535	Z-Di	bidirektional, 3,45V, 5%, 0,5W	31a	USA, Sie	—
1N4536	Si-Di	SS, 25V, 0,075A, <2ns	31a	USA, Hit	BA218, BAX13, BAX91, 1N4148..49, ++
1N4537	Si-Di	Gl-L, 1800V, 3A	32a	USA	—
1N4538	Si-Di	=1N4537: 2400V	32a		—
1N4539	Si-Di	=1N4537: 3000V	32a		—
1N454	Ge-Di	Uni, 60V	31a	USA	AA136, 1N270
1N4540	Si-Di	=1N4537: 3600V	32a		—
1N4541	Si-Di	Gl, 225V, 0,4A	31a	Sem, Trw	BA157..159, BY204/4, BY206..207, ++
1N4542	Si-Di	=1N4541: 400V	31a		BA157..159, BY204/4, BY207, ++
1N4543	Si-Di	=1N4541: 600V	31a		BA158..159, BY204/8, BY207, ++
1N4544	Si-Di	=1N4541: 600V	31a		BA159, BY204/8, BY208/800, ++
1N4545	Si-Di	=1N4541: 1000V	31a		BA159, BY204/10, BY208/1000, ++
1N4546	Si-Di	kV-Gl, 25kV, 1A		Sem	—
1N4547	Si-Di	HF/S, 25V, <60ns		Idc, Sem	—
1N4548	Si-Di	Min, SS, 25V, <2ns	31a	Idc, Sem	(BA217, BA317, BAY71, 1N4148..49, ++)
1N4549	Z-Di	3,9V, 20%, 50W(Tc=75°)	32b	USA, Mot, Sie	—
1N4549A..4556A	Z-Di	=1N4549..4556: 10%	32b		—
1N4549B..4556B	Z-Di	=1N4549..4556: 5%	32b		—
1N4549R..4556R	Z-Di	=1N4549..4556:	32a		—
1N455	Ge-Di	Uni, 35V	31a	USA	AA136, AA139, 1N270
1N4550	Z-Di	=1N4549: 4,3V	32b		—
1N4551	Z-Di	=1N4549: 4,7V	32b		—
1N4552	Z-Di	=1N4549: 5,1V	32b		—
1N4553	Z-Di	=1N4549: 5,6V	32b		—
1N4554	Z-Di	=1N4549: 6,2V	32b		—
1N4555	Z-Di	=1N4549: 6,8V	32b		—
1N4556	Z-Di	=1N4549: 7,5V	32b		—
1N4557	Z-Di	3,9V, 20%, 50W(Tc=75°)	23n	USA, Mot, Sie	—
1N4557A..4564A	Z-Di	=1N4557..4564: 10%	23n		—
1N4557B..4564B	Z-Di	=1N4557..4564: 5%	23n		—
1N4557R..4564R	Z-Di	=1N4557..4564:	23f		—
1N4558	Z-Di	=1N4557: 4,3V	23n		—
1N4559	Z-Di	=1N4557: 4,7V	23n		—
1N456(A)	Si-Di	Uni, 35V, 0,09..0,2A	31a	Fch, Tix, ++	BA127, BA187..190, BA215, 1N484A, ++
1N4560	Z-Di	=1N4557: 5,1V	23n		—
1N4561	Z-Di	=1N4557: 5,6V	23n		—
1N4562	Z-Di	=1N4557: 6,2V	23n		—
1N4563	Z-Di	=1N4557: 6,8V	23n		—
1N4564	Z-Di	=1N4557: 7,5V	23n		—
1N4565(A,B)	Ref-Di	6,4V, 5%, 0,4W	31a	USA, Sie, Tho	BZV10, BZV27, BZX90
1N4566(A,B)	Ref-Di	6,4V, 5%, 0,4W	31a		BZV11, BZV28, BZX91
1N4567(A,B)	Ref-Di	6,4V, 5%, 0,4W	31a		BZV12, BZV29, BZX92
1N4568(A,B)	Ref-Di	6,4V, 5%, 0,4W	31a		BZV13, BZV30, BZX93
1N4569(A,B)	Ref-Di	6,4V, 5%, 0,4W	31a		BZ+F4682V14, BZV31, BZX94
1N457(A)	Si-Di	Uni, 75V, 0,075..0,2A	31a	Fch, Tix, ++	BA188..190, BAY45, BAY73, 1N484A, ++
1N4570(A,B)	Ref-Di	6,4V, 5%, 0,4W	31a		—
1N4571(A,B)	Ref-Di	6,4V, 5%, 0,4W	31a		—
1N4572(A,B)	Ref-Di	6,4V, 5%, 0,4W	31a		—
1N4573(A,B)	Ref-Di	6,4V, 5%, 0,4W	31a		—
1N4574(A,B)	Ref-Di	6,4V, 5%, 0,4W	31a		—
1N4575(A,B)	Ref-Di	6,4V, 5%, 0,4W	31a		—
1N4576(A,B)	Ref-Di	6,4V, 5%, 0,4W	31a		—
1N4577(A,B)	Ref-Di	6,4V, 5%, 0,4W	31a		—
1N4578(A,B)	Ref-Di	6,4V, 5%, 0,4W	31a		—
1N4579(A,B)	Ref-Di	6,4V, 5%, 0,4W	31a		—
1N458(A)	Si-Di	Uni, 150V, 0,055..0,2A	31a	Fch, Tix, ++	BA189..190, BAY45, BAW52, 1N484A, ++
1N4560(A,B)	Ref-Di	6,4V, 5%, 0,4W	31a		—
1N4561(A,B)	Ref-Di	6,4V, 5%, 0,4W	31a		—
1N4562(A,B)	Ref-Di	6,4V, 5%, 0,4W	31a		—
1N4583(A,B)	Ref-Di	6,4V, 5%, 0,4W	31a		—
1N4564(A,B)	Ref-Di	6,4V, 5%, 0,4W	31a		—

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1N4585(GP)	Si-Di	Gl, 800V, 1A	31a	USA, Gie, Tho	BY127, BY133, BY227, 1N4006..07, ++
1N4586(GP)	Si-Di	=1N4585: 1000V	31a		BY127, BY133, BY227, 1N4007, ++
1N4587	Si-Di	Gl-L, 100V, 150A(Tc=110°)	73a	USA	—
1N4587R..4596R	Si-Di	=1N4587..4596	73b		—
1N4588	Si-Di	=1N4587: 200V	73a		—
1N4589	Si-Di	=1N4587: 300V	73a		—
1N459(A)	Si-Di	Uni, 200V, 0,04..0,2A	31a	Fch, Tix, ++	BA190, BAY46, BAW52, BAY20..21, ++
1N4590	Si-Di	=1N4587: 400V	73a		—
1N4591	Si-Di	=1N4587: 500V	73a		—
1N4592	Si-Di	=1N4587: 800V	73a		—
1N4593	Si-Di	=1N4587: 800V	73a		—
1N4594	Si-Di	=1N4587: 1000V	73a		—
1N4595	Si-Di	=1N4587: 1200V	73a		—
1N4596	Si-Di	=1N4587: 1400V	73a		—
1N4598(A)	Si-Di	VHF-Tuning, 90V	31a	Tdy	—
1N4599(A)	Si-Di	VHF-Tuning, 110V	31a	Tdy	—
1N46	Ge-Di	Uni, 60V, 40mA	31a	USA	AA117..118, AA132..134, 1N34, 1N54
1N460(A,B)	Si-Di	Uni, S, 90V, 0,045A		USA	BA147/100, BA189..190, 1N5195..96, ++
1N4600	Si-Di	UHF, M-Band-M, 10..16GHz	Koax	Miv, Sld	—
1N4601	Si-Di	UHF, M-Band-M, 10..16GHz	Koax	Miv, Sld	—
1N4602	Si-Di	UHF, M-Band-M, 10..18GHz	Koax	USA	—
1N4603	Si-Di	UHF, Ku-Band-M, 12,5..17,5GHz	Koax	USA	—
1N4604	Si-Di	UHF, Ku-Band-M, 12,5..17,5GHz	Koax	USA	—
1N4605	Si-Di	UHF, Ku-Band-M, 12,5..17,5GHz	Koax	USA	—
1N4606	Si-Di	SS, 85V, 0,35A, <8ns	31a	USA, Tix	BAV10, BAW55, BAW76, BAX81
1N4607	Si-Di	SS, 85V, 0,35A, <15ns	31a	USA, Tix	BAV10, BAW55, BAW76, BAX81
1N4608	Si-Di	SS, 85V, 0,35A, <15ns	31a	USA, Tix	BAV10, BAW55, BAW76, BAX81
1N4609(A)	Si-Di	VHF-Tuning	31a	Idc, Msc	—
1N461(A)	Si-Di	Uni, 30V, 0,06..0,2A	31a	Fch, Tix, ++	BA127, BA187..190, BA215, 1N484A, ++
1N4610	Si-Di	SS, 60V, <4ns	31a	USA	BAW62, BAW76, BAX95, 1N4146..49, ++
1N4611(A,B,C)	Ref-Di	8,6V, 5%, 0,25W	31a	USA	BZV11..14, BZV28..31, 1N4575..84, ++
1N4612(A,B,C)	Ref-Di	8,6V, 5%, 0,25W	31a		—
1N4613(A,B,C)	Ref-Di	6,6V, 5%, 0,25W	31a		—
1N4614	Z-Di	ra, 1,8V, 5%, 0,25W	31a	USA, Sie, Tho	—
1N4615	Z-Di	=1N4614: 2V	31a		—
1N4616	Z-Di	=1N4614: 2,2V	31a		—
1N4617	Z-Di	=1N4614: 2,4V	31a		—
1N4618	Z-Di	=1N4614: 2,7V	31a		—
1N4619	Z-Di	=1N4614: 3V	31a		—
1N462(A)	Si-Di	Uni, 70V, 0,05..0,2A	31a	Fch, Tix, ++	BA127, BA188..190, BA215, 1N484A, ++
1N4620	Z-Di	=1N4614: 3,3V	31a		—
1N4621	Z-Di	=1N4614: 3,6V	31a		—
1N4622	Z-Di	=1N4614: 3,9V	31a		—
1N4623	Z-Di	=1N4614: 4,3V	31a		—
1N4624	Z-Di	=1N4614: 4,7V	31a		—
1N4625	Z-Di	=1N4614: 5,1V	31a		—
1N4626	Z-Di	=1N4614: 5,6V	31a		—
1N4627	Z-Di	=1N4614: 6,2V	31a		—
1N4628	Z-Di	6,8V, 5%, 0,6W	31a	USA, Sie	BZX55/.., BZX83/.., ZPD.., 1N5235..61, ++
1N4629	Z-Di	=1N4628: 7,5V	31a		—
1N463(A)	Si-Di	Uni, 200V, 0,03..0,2A	31a	Fch, Tix, ++	BA190, BAW52, BAY46, BAY21, ++
1N4630	Z-Di	=1N4628: 8,2V	31a		—
1N4631	Z-Di	=1N4628: 9,1V	31a		—
1N4632	Z-Di	=1N4628: 10V	31a		—
1N4633	Z-Di	=1N4628: 11V	31a		—
1N4634	Z-Di	=1N4628: 12V	31a		—
1N4635	Z-Di	=1N4628: 13V	31a		—
1N4636	Z-Di	=1N4628: 15V	31a		—
1N4637	Z-Di	=1N4628: 16V	31a		—
1N4638	Z-Di	=1N4628: 18V	31a		—
1N4639	Z-Di	=1N4628: 20V	31a		—
1N464(A)	Si-Di	Uni, 150V, 0,04..0,2A	31a	Fch, Tix, ++	BA189..190, BAW52, BAY45, 1N484A, ++
1N4640	Z-Di	=1N4628: 22V	31a		—
1N4641	Z-Di	=1N4628: 24V	31a		—
1N4642	Z-Di	=1N4628: 27V	31a		—
1N4643	Z-Di	=1N4628: 30V	31a		—

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1N4644	Z-Di	=1N4628: 33V	31a		—
1N4645	Z-Di	=1N4628: 36V	31a		—
1N4646	Z-Di	=1N4628: 39V	31a		—
1N4647	Z-Di	=1N4628: 43V	31a		—
1N4648	Z-Di	=1N4628: 47V	31a		—
1N4649	Z-Di	3,3V,5%, 1W	31a	USA	BZW22/.., BZX61/.., ZPY.., 1N5913..41,++
1N465	Z-Di	2,6V, 10%, 0,25W	2c	USA	BZX55/.., BZX79/.., ZPD.., 1N5221..39,++
1N4650	Z-Di	=1N4649: 3,6V	31a		—
1N4651	Z-Di	=1N4649: 3,9V	31a		—
1N4652	Z-Di	=1N4649: 4,3V	31a		—
1N4653	Z-Di	=1N4649: 4,7V	31a		—
1N4654	Z-Di	=1N4649: 5,1V	31a		—
1N4655	Z-Di	=1N4649: 5,6V	31a		—
1N4656	Z-Di	=1N4649: 6,2V	31a		—
1N4657	Z-Di	=1N4649: 6,8V	31a		—
1N4658	Z-Di	=1N4649: 7,5V	31a		—
1N4659	Z-Di	=1N4649: 8,2V	31a		—
1N465A...470A	Z-Di	=1N465...470: 5%	2c		—
1N465B...470B	Z-Di	=1N465...470: 1%	2c		—
1N466	Z-Di	=1N465: 3,5V	2c		—
1N4660	Z-Di	=1N4649: 9,1V	31a		—
1N4661	Z-Di	=1N4649: 10V	31a		—
1N4662	Z-Di	=1N4649: 11V	31a		—
1N4663	Z-Di	=1N4649: 12V	31a		—
1N4664	Z-Di	=1N4649: 13V	31a		—
1N4665	Z-Di	=1N4649: 15V	31a		—
1N4666	Z-Di	=1N4649: 16V	31a		—
1N4667	Z-Di	=1N4649: 18V	31a		—
1N4668	Z-Di	=1N4649: 20V	31a		—
1N4669	Z-Di	=1N4649: 22V	31a		—
1N467	Z-Di	=1N465: 4,1V	2c		—
1N4670	Z-Di	=1N4649: 24V	31a		—
1N4671	Z-Di	=1N4649: 27V	31a		—
1N4672	Z-Di	=1N4649: 30V	31a		—
1N4673	Z-Di	=1N4649: 33V	31a		—
1N4674	Z-Di	=1N4649: 39V	31a		—
1N4675	Z-Di	=1N4649: 39V	31a		—
1N4678	Z-Di	=1N4649: 43V	31a		—
1N4677	Z-Di	=1N4649: 47V	31a		—
1N4678	Z-Di	1,8V,5%,0,25W	31a	USA,Mot,Sie	BZX79/.., BZX55/.., ZPD.., 1N5221..60,++
1N4679	Z-Di	=1N4678: 2V	31a		—
1N468	Z-Di	=1N465: 4,85V	2c		—
1N4680	Z-Di	=1N4678: 2,2V	31a		—
1N4681	Z-Di	=1N4678: 2,4V	31a		—
1N4682	Z-Di	=1N4678: 2,7V	31a		—
1N4683	Z-Di	=1N4678: 3V	31a		—
1N4684	Z-Di	=1N4678: 3,3V	31a		—
1N4685	Z-Di	=1N4678: 3,6V	31a		—
1N4686	Z-Di	=1N4678: 3,9V	31a		—
1N4687	Z-Di	=1N4678: 4,3V	31a		—
1N4688	Z-Di	=1N4678: 4,7V	31a		—
1N4689	Z-Di	=1N4678: 5,1V	31a		—
1N469	Z-Di	=1N465: 5,8V	2c		—
1N4690	Z-Di	=1N4678: 5,6V	31a		—
1N4691	Z-Di	=1N4678: 6,2V	31a		—
1N4692	Z-Di	=1N4678: 6,8V	31a		—
1N4693	Z-Di	=1N4678: 7,5V	31a		—
1N4694	Z-Di	=1N4678: 8,2V	31a		—
1N4695	Z-Di	=1N4678: 8,7V	31a		—
1N4696	Z-Di	=1N4678: 9,1V	31a		—
1N4697	Z-Di	=1N4678: 10V	31a		—
1N4698	Z-Di	=1N4678: 11V	31a		—
1N4699	Z-Di	=1N4678: 12V	31a		—
1N47	Ge-Di	Uni, 150V, 30mA	31a	USA	AA133, 1N39
1N470	Z-Di	=1N465: 7,1V	2c		—
1N4700	Z-Di	=1N4678: 13V	31a		—

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1N4701	Z-Di	=1N4678: 14V	31a		—
1N4702	Z-Di	=1N4678: 15V	31a		—
1N4703	Z-Di	=1N4678: 16V	31a		—
1N4704	Z-Di	=1N4678: 17V	31a		—
1N4705	Z-Di	=1N4678: 18V	31a		—
1N4706	Z-Di	=1N4678: 19V	31a		—
1N4707	Z-Di	=1N4678: 20V	31a		—
1N4708	Z-Di	=1N4678: 22V	31a		—
1N4709	Z-Di	=1N4678: 24V	31a		—
1N471	Z-Di	3+C4916,5V, 10%, 0,2W	2c	USA	BZX55/.., BZX79/.., ZPD.., 1N5221..36,++
1N4710	Z-Di	=1N4678: 25V	31a		—
1N4711	Z-Di	=1N4878: 27V	31a		—
1N4712	Z-Di	=1N4878: 28V	31a		—
1N4713	Z-Di	=1N4878: 30V	31a		—
1N4714	Z-Di	=1N4678: 33V	31a		—
1N4715	Z-Di	=1N4678: 36V	31a		—
1N4718	Z-Di	=1N4678: 39V	31a		—
1N4717	Z-Di	=1N4678: 43V	31a		—
1N4718	Si-Di	S, 50V, <180ns	31a	USA	BYT 52A, BYX92/50, MR810, RGP 10A,++
1N4719	Si-Di	GI, 50V, 3A	34a	USA, Mot	BY 398..399, RGP 30A, (BY 205/100,++)
1N4719R...4725R	Si-Di	=1N4719..4725:	34b		→1N4719..4725
1N471A...475A	Z-Di	=1N471..475: 5%	2c		—
1N471B...475B	Z-Di	=1N471..475: 1%	2c		—
1N472	Z-Di	=1N471: 4,1V	2c		—
1N4720	Si-Di	=1N4719: 100V	34a		BY 398..399, RGP 30B, (BY 205/100,++)
1N4721	Si-Di	=1N4719: 200V	34a		BY 397..399, RGP 30D, (BY 205/200,++)
1N4722	Si-Di	=1N4719: 400V	34a		BY 398..399, RGP 30G, (BY 205/400,++)
1N4723	Si-Di	=1N4719: 600V	34a		BY 228, BY 399, RPG 30J, (BY 205/600,++)
1N4724	Si-Di	=1N4719: 600V	34a		BY 228, BY 399, RGP 30K, (BY 205/800,++)
1N4725	Si-Di	=1N4719: 1000V	34a		BY 228, BY 436, RGP 30M, (BY 206/1000,++)
1N4726	Si-Di	SS, 20V, 0,06A	31a	USA, Tix,++	—
1N4727	Si-Di	SS, 20V, 0,075A	31a	USA, Tix	—
1N4726	Z-Di	3,3V, 10%, 1W	31a	USA, EUR, Hn	BZW22/.., BZX61/.., ZPY.., 1N5913..49,++
1N4728A..4764A	Z-Di	=1N4728..4764: 5%	31a		—
1N4729	Z-Di	=1N4728: 3,6V	31a		—
1N473	Z-Di	=1N471: 4,85V	2c		—
1N4730	Z-Di	=1N4728: 3,9V	31a		—
1N4731	Z-Di	=1N4728: 4,3V	31a		—
1N4732	Z-Di	=1N3728: 4,7V	31a		—
1N4733	Z-Di	=1N4728: 5,1V	31a		—
1N4734	Z-Di	=1N4728: 5,6V	31a		—
1N4735	Z-Di	=1N4728: 8,2V	31a		—
1N4736	Z-Di	=1N4728: 6,8V	31a		—
1N4737	Z-Di	=1N4728: 7,5V	31a		—
1N4739	Z-Di	=1N4728: 8,2V	31a		—
1N4739	Z-Di	=1N4728: 9,1V	31a		—
1N474	Z-Di	=1N471: 5,8V	2c		—
1N4740	Z-Di	=1N4728: 10V	31a		—
1N4741	Z-Di	=1N4728: 11V	31a		—
1N4742	Z-Di	=1N4728: 12V	31a		—
1N4743	Z-Di	=1N4728: 13V	31a		—
1N4744	Z-Di	=1N4728: 15V	31a		—
1N4745	Z-Di	=1N4728: 16V	31a		—
1N4746	Z-Di	=1N4728: 18V	31a		—
1N4747	Z-Di	=1N4728: 20V	31a		—
1N4748	Z-Di	=1N4728: 22V	31a		—
1N4749	Z-Di	=1N4728: 24V	31a		—
1N475	Z-Di	=1N471: 7,1V	2c		—
1N4750	Z-Di	=1N4728: 27V	31a		—
1N4751	Z-Di	=1N4728: 30V	31a		—
1N4752	Z-Di	=1N4728: 33V	31a		—
1N4753	Z-Di	=1N4728: 36V	31a		—
1N4754	Z-Di	=1N4728: 39V	31a		—
1N4755	Z-Di	=1N4728: 43V	31a		—
1N4756	Z-Di	=1N4728: 47V	31a		—
1N4757	Z-Di	=1N4728: 51V	31a		—

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1N4758	Z-Di	=1N4728: 56V	31a		—
1N4759	Z-Di	=1N4728: 62V	31a		—
1N476	Ge-Di	Uni, 90V, 50mA	31a	USA	AA117..118, AA132..133
1N4760	Z-Di	=1N4728: 68V	31a		—
1N4761	Z-Di	=1N4728: 75V	31a		—
1N4762	Z-Di	=1N4728: 62V	31a		—
1N4763	Z-Di	=1N4728: 91V	31a		—
1N4764	Z-Di	=1N4728: 100V	31a		—
1N4765(A,B)	Ref-Di	9,1V, 5%, 0,25W	31a	USA, Sie, Tho	1N935
1N4766(A,B)	Ref-Di	9,1V, 5%, 0,25W	31a		1N936
1N4767(A,B)	Ref-Di	9,1V, 5%, 0,25W	31a		1N937
1N4768(A,B)	Ref-Di	9,1V, 5%, 0,25W	31a		1N936
1N4769(A,B)	Ref-Di	9,1V, 5%, 0,25W	31a		1N939
1N477	Ge-Di	Uni, 90V, 50mA	31a	USA	AA117..118, AA132..133
1N4770(A,B)	Ref-Di	9,1V, 5%, 0,25W	31a		—
1N4771(A,B)	Ref-Di	9,1V, 5%, 0,25W	31a		—
1N4772(A,B)	Ref-Di	9,1V, 5%, 0,25W	31a		—
1N4773(A,B)	Ref-Di	9,1V, 5%, 0,25W	31a		—
1N4774(A,B)	Ref-Di	9,1V, 5%, 0,25W	31a		—
1N4775(A,B)	Ref-Di	8,5V, 5%, 0,25W	31a		1N3154
1N4776(A,B)	Ref-Di	8,5V, 5%, 0,25W	31a		1N3155
1N4777(A,B)	Ref-Di	8,5V, 5%, 0,25W	31a		1N3156
1N4778(A,B)	Ref-Di	8,5V, 5%, 0,25W	31a		1N3157
1N4779(A,B)	Ref-Di	8,5V, 5%, 0,25W	31a		—
1N478	Ge-Di	Uni, 90V, 50mA	31a	USA	AA117..118, AA132..133
1N4780(A,B)	Ref-Di	8,5V, 5%, 0,25W	31a		1N3154
1N4781(A,B)	Ref-Di	6,5V, 5%, 0,25W	31a		1N3155
1N4782(A,B)	Ref-Di	8,5V, 5%, 0,25W	31a		1N3156
1N4783(A,B)	Ref-Di	8,5V, 5%, 0,25W	31a		1N3157
1N4784(A,B)	Ref-Di	8,5V, 5%, 0,25W	31a		—
1N4785	Ge-Di	TV-Damper/Booster-Di, 320V, 7A	23	Rca	AY102
1N4786(A..D)	Si-Di	VHF-Tuning	31a	Tdy, Trw	—
1N4787(A...D)	Si-Di	VHF-Tuning	31a	Tdy, Trw	—
1N4788(A...D)	Si-Di	VHF-Tuning	31a	Tdy, Trw	—
1N4789(A...D)	Si-Di	VHF-Tuning	31a	Tdy, Trw	—
1N479	Ge-Di	Uni, 90V, 50mA	31a	USA	AA117..118, AA132..133
1N4790(A...D)	Si-Di	VHF-Tuning	31a	Tdy, Trw	—
1N4791(A...D)	Si-Di	VHF-Tuning	31a	Tdy, Trw	—
1N4792(A...D)	Si-Di	VHF-Tuning	31a	Tdy, Trw	—
1N4793(A...D)	Si-Di	VHF-Tuning	31a	Tdy, Trw	—
1N4794(A...D)	Si-Di	VHF-Tuning	31a	Tdy, Trw	—
1N4795(A...D)	Si-Di	VHF-Tuning	31a	Tdy, Trw	—
1N4796(A...D)	Si-Di	VHF-Tuning	31a	Tdy, Trw	—
1N4797(A...D)	Si-Di	VHF-Tuning	31a	Tdy, Trw	—
1N4798(A...D)	Si-Di	VHF-Tuning	31a	Tdy, Trw	—
1N4799(A...D)	Si-Di	VHF-Tuning	31a	Tdy, Trw	—
1N48	Ge-Di	Uni, 80V, 50mA	31a	USA, Tho	AA117..118, AA132..133
1N480	Ge-Di	S, 80V, 35mA, <500ns	31a	USA	AAY28, AAZ15, AAZ17, 1N276
1N4800(A...D)	Si-Di	VHF-Tuning	31a	Tdy, Trw	—
1N4801(A...D)	Si-Di	VHF-Tuning	31a	Tdy, Trw	—
1N4802(A...D)	Si-Di	VHF-Tuning	31a	Tdy, Trw	—
1N4803(A...D)	Si-Di	VHF-Tuning	31a	Tdy, Trw	—
1N4804(A...D)	Si-Di	VHF-Tuning	31a	Tdy, Trw	—
1N4805(A...D)	Si-Di	VHF-Tuning	31a	Tdy, Trw	—
1N4806(A...D)	Si-Di	VHF-Tuning	31a	Tdy, Trw	—
1N4807(A...D)	Si-Di	VHF-Tuning	31a	Tdy, Trw	—
1N4808(A...D)	Si-Di	VHF-Tuning	31a	Tdy, Trw	—
1N4809(A...D)	Si-Di	VHF-Tuning	31a	Tdy, Trw	—
1N481	Ge-Di	GI, 200V, 0,1A			—
1N4810(A...D	Si-Di	VHF-Tuning	31a	Tdy, Trw	—
1N4811(A...D)	Si-Di	VHF-Tuning	31a	Tdy, Trw	—
1N4812(A...D)	Si-Di	VHF-Tuning	31a	Tdy, Trw	—
1N4813(A...D)	Si-Di	VHF-Tuning	31a	Tdy, Trw	—
1N4814(A...D)	Si-Di	VHF-Tuning	31a	Tdy, Trw	—
1N4815(A...D)	Si-Di	VHF-Tuning	31a	Tdy, Trw	—
1N4816(A)	Si-Di	GI, 50V, 1,5A	31a	USA, Gie	BY226..227, BY251..255, 1N5391..99,++

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1N4817(A)	Si-Di	=1N4816: 100V	31a		BY226..227, BY251..255, 1N5392..99,++
1N4818(A)	Si-Di	=1N4818: 200V	31a		BY228..227, BY251..255, 1N5393..99,++
1N4819(A)	Si-Di	=1N4818: 300V	31a		BY228..227, BY252..255, 1N5394..99,++
1N482(A...C)	Si-Di	Uni, 40V, 0,1..0,2A	31a	Fch, Tix,++	BA127, BA187..190, BA215, BAY45,++
1N4820(A)	Si-Di	=1N4816: 400V	31a		BY228..227, BY252..255, 1N5395..99,++
1N4821(A)	Si-Di	=1N4818: 500V	31a		BY226..227, BY253..255, 1N5396..99,++
1N4822(A)	Si-Di	=1N4816: 600V	31a		BY226..227, BY253..255, 1N5397..99,++
1N4823	Si-Di	GI, S, 100V, 1A, <100ns	34a	USA	BYV12..18, BYX92/100, EGP10B,++
1N4824	Si-Di	=1N4823: 200V	34a		BYV13..18, BYX92/200, EGP10D,++
1N4825	Si-Di	=1N4823: 400V	34a		BYT52G, BYV13..18, BYX92/400,++
1N4826	Si-Di	=1N4823: 800V	84a		BYT52J, BYV14..16, BYV36C,++
1N4827	Ge-Di	S, 30V, 200ns	31a	USA	AAY28, 1N631, 1N633
1N4826	Si-St	1,1V(100mA), 0,4W	31a	USA,Gen	—
1N4829	Si-St	=1N4828: 1,87V(100mA)	31a		—
1N483(A..C)	Si-Di	=1N482(A..C): 80V	31a	Fch, Tix,++	BA188..190, BAW52, BAY19, BAY45,++
1N4830	Si-St	=1N4826: 2,69V(100mA)	31a		—
1N4831	Z-Di	bidirektional, 9,1V, 20%, 1,2W	31a	USA, Tix	—
1N4831A...4860A	Z-Di	=1N4831..4860: 10%	31a		—
1N4831B...4860B	Z-Di	=1N4831..4860: 5%	31a		—
1N4832	Z-Di	=1N4831: 10V	31a		—
1N4833	Z-Di	=1N4831: 11V	31a		—
1N4834	Z-Di	=1N4831: 12V	31a		—
1N4835	Z-Di	=1N4831: 13V	31a		—
1N4836	Z-Di	=1N4831: 15V	31a		—
1N4837	Z-Di	=1N4831: 18V	31a		—
1N4836	Z-Di	=1N4831: 18V	31a		—
1N4839	Z-Di	=1N4831: 20V	31a		—
1N484(A...C)	Si-Di	=1N482(A..C): 150V	31a	Fch, Tix,++	BA189..190, BAW52, BAY20, BAY45,++
1N4840	Z-Di	=1N4831: 22V	31a		—
1N4841	Z-Di	=1N4831: 24V	31a		—
1N4842	Z-Di	=1N4831: 27V	31a		—
1N4843	Z-Di	=1N4831: 3+C49410V	31a		—
1N4844	Z-Di	=1N4831: 33V	31a		—
1N4845	Z-Di	=1N4831: 39V	31a		—
1N4848	Z-Di	=1N4831: 39V	31a		—
1N4847	Z-Di	=1N4831: 43V	31a		—
1N4848	Z-Di	=1N4831: 47V	31a		—
1N4849	Z-Di	=1N4831: 51V	31a		—
1N485(A..C)	Si-Di	=1N482(A..C): 200V	31a	Fch, Tix,++	BA190, BAW52, BAY21, BAY46,++
1N4850	Z-Di	=1N4831: 56V	31a		—
1N4851	Z-Di	=1N4831: 82V	31a		—
1N4852	Z-Di	=1N4831: 68V	31a		—
1N4853	Z-Di	=1N4831: 75V	31a		—
1N4854	Z-Di	=1N4831: 82V	31a		—
1N4855	Z-Di	=1N4831: 91V	31a		—
1N4856	Z-Di	=1N4831: 100V	31a		—
1N4857	Z-Di	=1N4831: 110V	31a		—
1N4858	Z-Di	=1N4831: 120V	31a		—
1N4859	Z-Di	=1N4831: 130V	31a		—
1N468(A,B)	Si-Di	Uni, 225V, 0,1..0,2A	31a	Gie, Tix,++	BA157..159, BAY21, BAY46, BAY88..90
1N4860	Z-Di	=1N4831: 150V	31a		—
1N4861	Si-Di	S, 40V, <1µs	31a	USAHit	BA127, BA147/50, BA187..190,++
1N4862	Si-Di	S, 70V, <1µs	31a	USAHit	BA127, BA147/100, BA188..190,++
1N4863	Si-Di	SS, 70V, 0,2A, <7ns	31a	USA,Gen,Hit	BAW82, BAW76, BAX95, 1N4148..49,++
1N4864	Si-Di	SS, 125V, 0,2A, <4ns	31a	USA,Gen,Hit	(BA203)
1N4865	Si-Di	kV-GI, 1,5kV, 1,25A		USA	—
1N4866	Si-Di	=1N4685: 2,5kV			—
1N4867	Si-Di	=1N4885: 3kV			—
1N4866	Si-Di	=1N4885: 5kV			—
1N4869	Si-Di	=1N4865: 7,5kV			—
1N487(A,B)	Si-Di	=1N488(A,B): 300V	31a		BA157..156, BAY21, BAY46, BAY68..90
1N4870	Si-Di	=1N4865: 10kV			—
1N4871	Si-Di	=1N4865: 12kV			—
1N4872	Si-Di	=1N4865: 15kV			—
1N4873	Si-Di	=1N4885: 20kV			—
1N4874	Si-Di	=1N4865: 25kV			—

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1N4875	Si-Di	=1N4865: 30kV			—
1N4876	Si-Di	=1N4865: 40kV			—
1N4877	Si-Di	=1N4865: 50kV			—
1N4878	Si-Di	GI-L, 100V, 100A(Tc=120°)	73a	USA	1N3288..97
1N4879	Si-Di	GI-L, 100V, 160A(Tc=120°)	73a	USA	1N4587..96
1N488(A,B)	Si-Di	=1N486(A,B): 380V	31a		BA158..159, BAY21, BAY88..90
1N4880	Si-Di	GI-L, 250V, 160A(Tc=120°)	73a		1N3735..44
1N4881	Z-Di	20V, 10%, 3W	31a	USA	BZT03/C,D20
1N4882	Z-Di	36V, 10%, 3W	31a	USA	BZT03/C,D36
1N4883	Z-Di	12V, 5%, 3W	31a	USA	BZT 03/C12
1N4884	Z-Di	=1N4881: 5%	31a		BZT 03/C20
1N4885	Si-Di	HF-Multipl	32	Phi	—
1N4886	Si-Di	HF-Multipl	32	Phi	—
1N4887	Si-Di	=1N4865: 75kV			—
1N4888	Si-Di	SS, 12V, <0,5ns	31a	Idc	BAY82, 1N4244, 1N4376
1N4889	Z-Di	82V, 5%, 5W	31a	Trw	BZV40/C82, BZV48/C82, 1N5372
1N4890(A)	Ref-Di	6,35V, 5%, 0,4W	31a	USA,Sie	—
1N4891(A)	Ref-Di	6,35V, 5%, 0,4W	31a		—
1N4892(A)	Ref-Di	6,35V, 5%, 0,4W	31a		—
1N4893(A)	Ref-Di	6,35V, 5%, 0,4W	31a		—
1N4894(A)	Ref-Di	6,35V, 5%, 0,4W	31a		—
1N4895(A)	Ref-Di	6,35V, 5%, 0,4W	31a		—
1N4896(A)	Ref-Di	ra, 12,8V, 5%, 0,4W	31a	Mot,Sie,++	—
1N4897(A)	Ref-Di	ra, 12,8V, 5%, 0,4W	31a		—
1N4898(A)	Ref-Di	ra, 12,8V, 5%, 0,4W	31a		—
1N4899(A)	Ref-Di	ra, 12,8V, 5%, 0,4W	31a		—
1N49	Ge-Di	Uni, 75V	31a	USA,Tho	AA117..118, AA132..133, 1N34, 1N54
1N490	Ge-Di	S, 60V, 35mA, <500ns	31a	USA	AAY28, AAZ15, AAZ17, 1N278
1N4900(A)	Ref-Di	ra, 12,8V, 5%, 0,4W	31a		—
1N4901(A)	Ref-Di	ra, 12,8V, 5%, 0,4W	31a		—
1N4902(A)	Ref-Di	ra, 12,8V, 5%, 0,4W	31a		—
1N4903(A)	Ref-Di	ra, 12,8V, 5%, 0,4W	31a		—
1N4904(A)	Ref-Di	ra, 12,8V, 5%, 0,4W	31a		—
1N4905(A)	Ref-Di	ra, 12,8V, 5%, 0,4W	31a		—
1N4906(A)	Ref-Di	ra, 12,8V, 5%, 0,4W	31a		—
1N4907(A)	Ref-Di	ra, 12,8V, 5%, 0,4W	31a		—
1N4908(A)	Ref-Di	ra, 12,8V, 5%, 0,4W	31a		—
1N4909(A)	Ref-Di	ra, 12,8V, 5%, 0,4W	31a		—
1N4910(A)	Ref-Di	ra, 12,8V, 5%, 0,4W	31a		—
1N4911(A)	Ref-Di	ra, 12,8V, 5%, 0,4W	31a		—
1N4912(A)	Ref-Di	ra, 12,8V, 5%, 0,4W	31a		—
1N4913(A)	Ref-Di	ra, 12,8V, 5%, 0,4W	31a		—
1N4914(A)	Ref-Di	ra, 12,8V, 5%, 0,4W	31a		—
1N4915(A)	Ref-Di	ra, 12,8V, 5%, 0,4W	31a		—
1N4916(A)	Ref-Di	ra, 19,2V, 5%, 0,4W	31a		—
1N4917(A)	Ref-Di	ra, 19,2V, 5%, 0,4W	31a		—
1N4918(A)	Ref-Di	ra, 19,2V, 5%, 0,4W	31a		—
1N4919(A)	Ref-Di	ra, 19,2V, 5%, 0,4W	31a		—
1N4920(A)	Ref-Di	ra, 19,2V, 5%, 0,4W	31a		—
1N4921(A)	Ref-Di	ra, 19,2V, 5%, 0,4W	31a		—
1N4922(A)	Ref-Di	ra, 19,2V, 5%, 0,4W	31a		—
1N4923(A)	Ref-Di	ra, 19,2V, 5%, 0,4W	31a		—
1N4924(A)	Ref-Di	ra, 19,2V, 5%, 0,4W	31a		—
1N4925(A)	Ref-Di	ra, 19,2V, 5%, 0,4W	31a		—
1N4926(A)	Ref-Di	ra, 19,2V, 5%, 0,4W	31a		—
1N4927(A)	Ref-Di	ra, 19,2V, 5%, 0,4W	31a		—
1N4928(A)	Ref-Di	ra, 19,2V, 5%, 0,4W	31a		—
1N4929(A)	Ref-Di	ra, 19,2V, 5%, 0,4W	31a		—
1N4930(A)	Ref-Di	ra, 19,2V, 5%, 0,4W	31a		—
1N4931(A)	Ref-Di	ra, 19,2V, 5%, 0,4W	31a		—
1N4932(A)	Ref-Di	ra, 19,2V, 5%, 0,4W	31a		—
1N4933(GP)	Si-Di	GI, S, 50V, 1A, <200ns	31a	USA,EUR	BYT52A, BYX92/50, EGP10A, RGP10A, ++
1N4934(GP)	Si-Di	=1N4933: 100V	31a		BYT52B, BYX92/100, EGP10B, RGP10B, ++
1N4935(GP)	Si-Di	=1N4933: 200V	31a		BYT52D, BYX92/200, EGP10D, RGP10D, ++
1N4936(GP)	Si-Di	=1N4933: 400V	31a		BY201/4, BYT52G, BYX92/400, RGP10G++
1N4937(GP)	Si-Di	=1N4933: 600V	31a		BY201/6, BYT52J, BYX92/600, RGP10J++

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1N4938	Si-Di	=1N3070	31a	USA,Fch,Hit	→1N3070
1N4939	Ge-Di	UHF, Ka-Band-M	Koax	Phi	—
1N4940	Ge-Di	UHF, X-Band-M	Koax	Phi	—
1N4941	GaAs-Di	UHF-Tuning	Koax	Phi	—
1N4942(GP)	Si-Di	Gl, S, 200V, 1A, <150ns	31a	USA,Sie,Tho	BYT52D, BYX92/200, EGP10D, RGP10D,++
1N4943(GP)	Si-Di	=1N4942: 300V	31a		BYT52G, BYX92/300, RGP10G,++
1N4944(GP)	Si-Di	=1N4942: 400V	31a		BYT52G, BYX92/400, RGP10G,++
1N4945(GP)	Si-Di	=1N4942: 500V	31a		BY201/6, BYT52J, RGP10J,++
1N4946(GP)	Si-Di	=1N4942: 600V, <250ns	31a		BY201/6, BYT52J, RGP10J,++
1N4947(GP)	Si-Di	=1N4942: 600V, <250ns	31a		BYV15..16, BYT52K, RGP10K,++
1N4948(GP)	Si-Di	=1N4942: 1000V, <500ns	31a		BYV16, BYV38, BYT52M, RGP10M,++
1N4949	Si-Di	SS, 35V, <0,3ns	31a	Idc,Inr	—
1N4950	Si-Di	SS, 30V, <4ns	31a	USA	BA216, BAX13, BAX91, 1N4146..49, ++
1N4951	Si-Di	Dual, TV-HA-Synchr. 20V, 25mA	7e	Gen	—
1N4952	Si-Di	=1N4951: 50V	7e	Gen	—
1N4953	Di	SS, 30V	Koax	Hew	—
1N4954	Z-Di	6,8V, 5%, 5W	31a	USA	BZV40/.., BZV48/.., 1N5342..5386
1N4954A...4996A	Z-Di	=1N4954..4996: 10%	31a		—
1N4954B...4996B	Z-Di	=1N4954..4996: 20%	31a		—
1N4955	Z-Di	=1N4954: 7,5V	31a		—
1N4956	Z-Di	=1N4954: 8,2V	31a		—
1N4957	Z-Di	=1N4954: 9,1V	31a		—
1N4956	Z-Di	=1N4954: 10V	31a		—
1N4959	Z-Di	=1N4954: 11V	31a		—
1N4960	Z-Di	=1N4954: 12V	31a		—
1N4961	Z-Di	=1N4954: 13V	31a		—
1N4962	Z-Di	=1N4954: 15V	31a		—
1N4963	Z-Di	=1N4954: 16V	31a		—
1N4964	Z-Di	=1N4954: 18V	31a		—
1N4965	Z-Di	=1N4954: 20V	31a		—
1N4966	Z-Di	=1N4954: 22V	31a		—
1N4967	Z-Di	=1N4954: 24V	31a		—
1N4968	Z-Di	=1N4954: 27V	31a		—
1N4969	Z-Di	=1N4954: 30V	31a		—
1N497	Ge-Di	Uni, 25V, 80mA	31a	USA	AA135..138, 1N270
1N4970	Z-Di	=1N4954: 33V	31a		—
1N4971	Z-Di	=1N4954: 38V	31a		—
1N4972	Z-Di	=1N4954: 39V	31a		—
1N4973	Z-Di	=1N4954: 43V	31a		—
1N4974	Z-Di	=1N4954: 47V	31a		—
1N4975	Z-Di	=1N4954: 51V	31a		—
1N4976	Z-Di	=1N4954: 56V	31a		—
1N4977	Z-Di	=1N4954: 62V	31a		—
1N4978	Z-Di	=1N4954: 68V	31a		—
1N4979	Z-Di	=1N4954: 75V	31a		—
1N498	Ge-Di	Uni, 46V, 70mA	31a	USA	AA136, 1N270
1N4980	Z-Di	=1N4954: 82V	31a		—
1N4981	Z-Di	=1N4954: 91V	31a		—
1N4962	Z-Di	=1N4954: 100V	31a		—
1N4963	Z-Di	=1N4954: 110V	31a		—
1N4964	Z-Di	=1N4954: 120V	31a		—
1N4965	Z-Di	=1N4954: 130V	31a		—
1N4966	Z-Di	=1N4954: 150V	31a		—
1N4967	Z-Di	=1N4954: 160V	31a		—
1N4968	Z-Di	=1N4954: 160V	31a		—
1N4989	Z-Di	=1N4954: 200V	31a		—
1N499	Ge-Di	Uni, 82V, 60mA	31a	USA	AA136, 1N270
1N4990	Z-Di	=1N4954: 220V	31a		—
1N4991	Z-Di	=1N4954: 240V	31a		—
1N4992	Z-Di	=1N4954: 270V	31a		—
1N4993	Z-Di	=1N4954: 300V	31a		—
1N4994	Z-Di	=1N4954: 330V	31a		—
1N4995	Z-Di	=1N4954: 360V	31a		—
1N4996	Z-Di	=1N4954: 390V	31a		—
1N4997(R)	Si-Di	≈1N4719		USA,Mot	→1N4719
1N4996(R)	Si-Di	≈1N4720		USA,Mot	→1N4720

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1N4999(R)	Si-Di	≈1N4721		USA, Mot	→1N4721
1N50	Ge-Di	Uni, 75V	31a	USA, Tho	AA117..118, AA132..133, 1N34, 1N54
1N500	Ge-Di	Uni, 70V, 80mA	31a	USA	1N270
1N5000(R)	Si-Di	≈1N4722		USA, Mot	→1N4722
1N5001(R)	Si-Di	≈1N4723		USA, Mot	→1N4723
1N5002(R)	Si-Di	≈1N4724		USA, Mot	→1N4724
1N5003(R)	Si-Di	≈1N4725		USA, Mot	→1N4725
1N5004	Si-Di	Gl, 100V, 1A	34a	USA	BY126..127, BY133..134, 1N4002..07,++
1N5005	Si-Di	=1N5004: 200V	34a		BY126..127, BY133..134, 1N4003..07,++
1N5006	Si-Di	=1N5004: 400V	34a		BY126..127, BY133..134, 1N4004..07,++
1N6007	Si-Di	=1N5004: 600V	34a		BY126..127, BY133..134, 1N4005..07,++
1N5006	Z-Di	3,3V, 10%, 2,5W	31a	USA	BZD23/.., BZT03/.., BZX70/..
1N5008A...5051A	Z-Di	=1N5008..5051: 5%	31a		—
1N5009	Z-Di	=1N5008: 3,6V	31a		—
1N501	Ge-Di	Uni, 92V, 80mA	31a	USA	1N270
1N5010	Z-Di	=1N5008: 3,9V	31a		—
1N5011	Z-Di	=1N5008: 4,3V	31a		—
1N5012	Z-Di	=1N5008: 4,7V	31a		—
1N5013	Z-Di	=1N5008: 5,1V	31a		—
1N5014	Z-Di	=1N5008: 5,6V	31a		—
1N5015	Z-Di	=1N5008: 6,2V	31a		—
1N5016	Z-Di	=1N5008: 6,8V	31a		—
1N5017	Z-Di	=1N5008: 7,5V	31a		—
1N5016	Z-Di	=1N5008: 8,2V	31a		—
1N5019	Z-Di	=1N5008: 9,1V	31a		—
1N502	Ge-Di	Uni, 115V, 70mA	31a	USA	1N270
1N5020	Z-Di	=1N5008: 10V	31a		—
1N5021	Z-Di	=1N5006: 11V	31a		—
1N5022	Z-Di	=1N5008: 12V	31a		—
1N5023	Z-Di	=1N5008: 13V	31a		—
1N5024	Z-Di	=1N5008: 14V	31a		—
1N5025	Z-Di	=1N5008: 15V	31a		—
1N5026	Z-Di	=1N5008: 16V	31a		—
1N5027	Z-Di	=1N5008: 17V	31a		—
1N5026	Z-Di	=1N5008: 16V	31a		—
1N5029	Z-Di	=1N5008: 19V	31a		—
1N503	Si-Di	Gl, 50V, 0,33A		old	BY126..127, BY133..135, 1N4001..07,++
1N5030	Z-Di	=1N5008; 20V	31a		—
1N5031	Z-Di	=1N5008: 22V	31a		—
1N5032	Z-Di	=1N5008: 24V	31a		—
1N5033	Z-Di	=1N5008: 25V	31a		—
1N5034	Z-Di	=1N5008: 27V	31a		—
1N5035	Z-Di	=1N5008: 30V	31a		—
1N5036	Z-Di	=1N5008: 33V	31a		—
1N5037	Z-Di	=1N5008: 36V	31a		—
1N5036	Z-Di	=1N5008: 39V	31a		—
1N5039	Z-Di	=1N5008: 43V	31a		—
1N504	Si-Di	=1N503: 100V			BY126..127, BY133..135, 1N4002..07,++
1N5040	Z-Di	=1N5008: 45V	31a		—
1N5041	Z-Di	=1N5008: 47V	31a		—
1N5042	Z-Di	=1N5008: 50V	31a		—
1N5043	Z-Di	=1N5008: 51V	31a		—
1N5044	Z-Di	=1N5008: 52V	31a		—
1N5045	Z-Di	=1N5008: 56V	31a		—
1N5046	Z-Di	=1N5008: 62V	31a		—
1N5047	Z-Di	=1N5008: 68V	31a		—
1N5048	Z-Di	=1N5008: 75V	31a		—
1N5049	Z-Di	=1N5006: 82V	31a		—
1N505	Si-Di	=1N503: 200V			BY126..127, BY133..134, 1N4003..07,++
1N5050	Z-Di	=1N5006: 91V	31a		—
1N5051	Z-Di	=1N5006: 100V	31a		—
1N5052(A)	Si-Di	Gl, 700V, 1,5A	31a	USA	BY227, BYX85..86, GP15K, 1N5398..99++
1N5053(A)	Si-Di	=1N5052: 800V	31a		BY227, BYX85..68, GP15K, 1N5398..99++
1N5054(A)	Si-Di	=1N5052: 1000V	31a		BY227, BYX68, GP15M, 1N5399,++
1N5055	Si-Di	Gl, 100V, 1A	31a	USA	BY126..127, BY133..135, 1N4002..07,++
1N5056	Si-Di	=1N5055: 200V	31a		BY126..127, BY133..134, 1N4003..07,++

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1N5057	Si-Di	=1N5055: 300V, 0,8A	31a		BY126..127, BY133..134, 1N4004..07,++
1N5058	Si-Di	=1N5055: 400V, 0,8A	31a		BY126..127, BY133..134, 1N4004..07,++
1N5059(GP)	Si-Di	Gl,contr.av., 200V, 2A	31a	USA,EUR,Hit	BYD14D..M, BYW52..58
1N506	Si-Di	=1N503: 300V			BY126..127, BY133..134, 1N4004..07,++
1N5060(GP)	Si-Di	=1N5059: 400V	31a		BYD14G..M, BYW53..58
1N5061(GP)	Si-Di	=1N5059: 600V	31a		BYD14J..M, BYW54..56
1N5062(GP)	Si-Di	=1N5059: 600V	31a		BYD14K..M, BYW55..58
1N5063	Z-Di	6,8V, 5%, 3W	31a	USA	BZT03/..
1N5064	Z-Di	=1N5063: 7,5V	31a		—
1N5065	Z-Di	=1N5063: 8,2V	31a		—
1N5066	Z-Di	=1N5063: 9,1V	31a		—
1N5067	Z-Di	=1N5063: 10V	31a		—
1N5066	Z-Di	=1N5063: 11V	31a		—
1N5069	Z-Di	=1N5063: 13V	31a		—
1N507	Si-Di	=1N503: 400V			BY126..127, BY133..134, 1N4004..07,++
1N5070	Z-Di	=1N5063: 14V	31a		—
1N5071	Z-Di	=1N5063: 15V	31a		—
1N5072	Z-Di	=1N5063: 16V	31a		—
1N5073	Z-Di	=1N5063: 18V	31a		—
1N5074	Z-Di	=1N5063: 22V	31a		—
1N5075	Z-Di	=1N5063: 24V	31a		—
1N5076	Z-Di	=1N5063: 27V	31a		—
1N5077	Z-Di	=1N5063: 30V	31a		—
1N5078	Z-Di	=1N5063: 33V	31a		—
1N5079	Z-Di	=1N5063: 36V	31a		—
1N506	Si-Di	=1N503: 600V			BY126..127, BY133..134, 1N4005..07,++
1N5080	Z-Di	=1N5063: 39V	31a		—
1N5081	Z-Di	=1N5063: 40V	31a		—
1N5082	Z-Di	=1N5063: 43V	31a		—
1N5083	Z-Di	=1N5063: 45V	31a		—
1N5084	Z-Di	=1N5063: 47V	31a		—
1N5085	Z-Di	=1N5063: 50V	31a		—
1N5066	Z-Di	=1N5063: 51V	31a		—
1N5067	Z-Di	=1N5063: 58V	31a		—
1N5088	Z-Di	=1N5063: 80V	31a		—
1N5069	Z-Di	=1N5063: 62V	31a		—
1N509	Si-Di	=1N503: 600V			BY127, BY133, BYW42, 1N4006..07,++
1N5090	Z-Di	=1N5063: 88V	31a		—
1N5091	Z-Di	=1N5063: 70V	31a		—
1N5092	Z-Di	=1N5063: 75V	31a		—
1N5093	Z-Di	=1N5063: 80V	31a		—
1N5094	Z-Di	=1N5063: 82V	31a		—
1N5065	Z-Di	=1N5063: 91V	31a		—
1N5096	Z-Di	=1N5063: 110V	31a		—
1N5097	Z-Di	=1N5063: 120V	31a		—
1N5088	Z-Di	=1N5063: 130V	31a		—
1N5099	Z-Di	=1N5063: 140V	31a		—
1N51	Ge-Di	Dem, Uni, 46V, 30mA	31a	USA,Tho	AA113, 1N34, 1N54, 1N60
1N510	Si-Di	=1N503: 1000V			BY127, BY133, BYW43, 1N4007,++
1N5100	Z-Di	=1N5063: 180V	31a		—
1N5101	Z-Di	=1N5063: 170V	31a		—
1N5102	Z-Di	=1N5063: 180V	31a		—
1N5103	Z-Di	=1N5063: 190V	31a		—
1N5104	Z-Di	=1N5063: 200V	31a		—
1N5105	Z-Di	=1N5063: 220V	31a		—
1N5106	Z-Di	=1N5063: 240V	31a		—
1N5107	Z-Di	=1N5063: 260V	31a		—
1N5108	Z-Di	=1N5063: 270V	31a		—
1N5109	Z-Di	=1N5063: 280V	31a		—
1N511	Si-Di	Gl, 50V, 1A		old	BY126..127, BY133..135, 1N4001..07,++
1N5110	Z-Di	=1N5063: 300V	31a		—
1N5111	Z-Di	=1N5063: 320V	31a		—
1N5112	Z-Di	=1N5063: 330V	31a		—
1N5113	Z-Di	=1N5063: 340V	31a		—
1N5114	Z-Di	=1N5063: 360V	31a		—
1N5115	Z-Di	=1N5063: 360V	31a		—

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1N5116	Z-Di	=1N5063: 390V	31a		—
1N5117	Z-Di	=1N5063: 400V	31a		—
1N5118	Z-Di	14V, 5%, 5W	31a	USA	BZV40/.., BZV48/.., 1N5351..5388
1N5119	Z-Di	=1N5118: 40V	31a		—
1N512	Si-Di	≥1N511: 100V			BY126..127, BY133..135, 1N4002..07,++
1N5120	Z-Di	=1N5118: 45V	31a		—
1N5121	Z-Di	=1N5118: 50V	31a		—
1N5122	Z-Di	=1N5118: 60V	31a		—
1N5123	Z-Di	=1N5118: 70V	31a		—
1N5124	Z-Di	=1N5118: 60V	31a		—
1N5125	Z-Di	=1N5118: 90V	31a		—
1N5126	Z-Di	=1N5118: 140V	31a		—
1N5127	Z-Di	=1N5118: 170V	31a		—
1N5128	Z-Di	=1N5118: 190V	31a		—
1N5129	Z-Di	=1N5118: 260V	31a		—
1N513	Si-Di	=1N511: 200V			BY128..127, BY133..134, 1N4003..07,++
1N5130	Z-Di	=1N5118: 260V	31a		—
1N5131	Z-Di	=1N5118: 320V	31a		—
1N5132	Z-Di	=1N5118: 340V	31a		—
1N5133	Z-Di	=1N5118: 380V	31a		—
1N5134	Z-Di	=1N5118: 400V	31a		—
1N5136(A)	Si-Di	VHF-Tuning	31a	Cod	—
1N5137(A)	Si-Di	VHF-Tuning	31a	Cod	—
1N5138(A)	Si-Di	VHF-Tuning	31a	Cod	—
1N5139(A)	Si-Di	VHF-Tuning	31a	USA,Mot,Tho	—
1N514	Si-Di	=1N511: 300V			BY128..127, BY133..134, 1N4004..07,++
1N5140(A)	Si-Di	VHF-Tuning	31a	USA,Mot,Tho	—
1N5141(A)	Si-Di	VHF-Tuning	31a	USA,Mot,Tho	—
1N5142(A)	Si-Di	VHF-Tuning	31a	USA,Mot,Tho	—
1N5143(A)	Si-Di	VHF-Tuning	31a	USA,Mot,Tho	—
1N5144(A)	Si-Di	VHF-Tuning	31a	USA,Mot,Tho	—
1N5145(A)	Si-Di	VHF-Tuning	31a	USA,Mot,Tho	—
1N5146(A)	Si-Di	VHF-Tuning	31a	USA,Mot,Tho	—
1N5147(A)	Si-Di	VHF-Tuning	31a	USA,Mot,Tho	—
1N5148(A)	Si-Di	VHF-Tuning	31a	USA,Mot,Tho	—
1N5149(A)	Si-Di	Step-recovery, UHF-Multipl	Koax	Far,Mot,Pai	—
1N515	Si-Di	=1N511: 400V			BY128..127, BY133..134, 1N4004..07,++
1N5150(A)	Si-Di	Step-recovery, UHF-Multipl	Koax	Fer,Mot,Pai	—
1N5151	Si-Di	Step-recovary, UHF-Multipl	Koax	Mot,Phi,++	—
1N5152(A)	Si-Di	Step-recovery, UHF-Multipl	Koax	Mot,Phi,++	—
1N5153(A)	Si-Di	Step-recovery, UHF-Multipl	Koax	Mot,Phi,++	—
1N5154	Si-Di	Step-recovery, UHF-Multipl	Koax	Mot,Phi,++	—
1N5155(A)	Si-Di	Step-recovery, UHF-Multipl	Koax	Mot,Phi,++	—
1N5156	Si-Di	Step-recovery, UHF-Multipl	Koax	Mot,Phi,++	—
1N5157	Si-Di	Step-recovery, UHF-Multipl	Koax	Mot,Phi,++	—
1N5158	Triggar-Di	Ub=8..C533110V, Ib<0,05mA, Itsm=10A	31a	Mot	—
1N5159	Triggar-Di	=1N5158: Ub=9..11V	31a		—
1N516	Si-Di	=1N511: 600V			BY128..127, BY133..134, 1N4005..07,++
1N5160	Triggar-Di	=1N5158: Ub=10..12V	31a		—
1N5161	Si-Di	Rauschdiode/noise diode	31a	Sol	—
1N5162	Si-Di	Gl-L, 1200V, 150A(Tc=150°)	78a	USA	1N4595..96
1N5163	Si-Di	Snap-off-Diode, SS, 35V, <0,5ns	31a	Hew	—
1N5164	Si-Di	Snap-off-Diode, SS, 35V, <0,4ns	31a	Hew	—
1N5165(A)	Si-Di	Schottky-Di, HF/S, 30V	31a	Hew	—
1N5168(A)	Si-Di	Schottky-Di, HF/S, 30V	31a	Hew	—
1N5167(A)	Si-Di	Schottky-Di, HF/S, 20V	31a	Hew	—
1N5168	Si-Di	Schottky-Di, HF	31a	Hew	—
1N5169	Si-Di	Schottky-Di, HF	31a	Hew	—
1N517	Si-Di	=1N511: 800V			BY127, BY133, BYW42, 1N4006..07,++
1N5170	Si-Di	Gl, 15V, 2A	31a	USA	BY251..255, BYW52..58, 1N5400..08,++
1N5171	Si-Di	=1N5170: 50V	31a		BY251..255, BYW52..58, 1N5400..08,++
1N5172	Si-Di	=1N5170: 100V	31a		BY251..255, BYW52..58, 1N5401..08,++
1N5173	Si-Di	=1N5170: 300V	31a		BY252..255, BYW53..58, 1N5404..08,++
1N5174	Si-Di	=1N5170: 400V	31a		BY252..255, BYW53..58, 1N5404..08,++
1N5175	Si-Di	=1N5170: 500V	31a		BY253..255, BYW54..58, 1N5406..08,++
1N5176	Si-Di	=1N5170: 600V	31a		BY253..255, BYW54..58, 1N5406..08,++

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1N5177	Si-Di	=1N5170: 800V	31a		BY254..255, BYW55..56, 1N5407..08,++
1N5178	Si-Di	=1N5170: 1000V	31a		BY255, BYW56, GP20M, 1N5408,++
1N5179	Si-St	2,8V(1mA), 0,4W	31a	Gen,Idc	BZ102/2V8, BZV86/2V6, BZX75/C2V8
1N518	Si-Di	=1N511: 1000V			BY127, BY133, BYW43, 1N4007,++
1N5180	Si-Di	Gl, 120V, 4A	31a	Sem,Trw	BY500/200, MR752..780, MR822..826,++
1N5181	Si-Di	kV-Gl, 4kV, 0,1A	31a	USA,Tho	HVG4, 1N1734
1N5182	Si-Di	=1N5181: 5kV	31a		HVG5, 1N1734
1N5183	Si-Di	=1N5181: 7,5kV	31a		BYX90
1N5184	Si-Di	=1N518: 10kV	31a		1N3052
1N5185(A)	Si-Di	Gl, S, 50V, 3..4A, <250..400ns	31a	USA,Gie	BY500/100, BYV61..63, MR820..826,++
1N5186(A)	Si-Di	=1N5185: 100V	31a		BY500/100, BYV62..63, MR821..826,++
1N5187(A)	Si-Di	=1N5185: 200V	31a		BY500/200, EGP50D, FE5D, MR822..826
1N5188(A)	Si-Di	=1N5185: 400V	31a		BY500/400, MR824..826
1N5189(A)	Si-Di	=1N5185: 500V	31a		BY500/600, MR826
1N519	Si-Di	Gl, 50V, 1,25A		old	BY126..127, BY133..135, 1N4001..07,++
1N5190(A)	Si-Di	=1N5185: 600V	31a		BY500/600, MR826
1N5194	Si-Di	Gl, Uni, 80V, 0,2A	31a	USA,Tix	BA157..159, BA186..190, BAY19..20,++
1N5195	Si-Di	=1N5194: 200V	31a		BA157..159, BA190, BAY21,++
1N5196	Si-Di	=1N5194: 250V	31a		BA157..159, BAY46, BAY88..90,++
1N5197	Si-Di	Gl, 50V, 3A	31a	USA	BY251..255, BYW17/100, 1N5400..08,++
1N5198	Si-Di	=1N5197: 100V	31a		BY251..255, BYW17/100, 1N5401..08,++
1N5199	Si-Di	=1N5197: 200V	31a		BY251..255, BYW17/200, 1N5402..08,++
1N52(A)	Ge-Di	Uni, 80V, 50mA	31a	USA,Tho	AA117..118, AA132..133
1N520	Si-Di	=1N519: 100V			BY126..127, BY133..135, 1N4002..07,++
1N5200	Si-Di	=1N5197: 400V	31a		BY252..255, BYW17/400, 1N5404..08,++
1N5201	Si-Di	=1N5197: 600V	31a		BY253..255, BYW17/600, 1N5406..08,++
1N5206	Si-Di	Gl, Uni, 440V, 2A	31a	Sem,Trw	BY253..255, BYW54..56, 1N5061..62,++
1N5207	Si-Di	Gl, Uni, 440V, 4A	31a	Sem,Trw	BY500/600, MR756..760, MR826
1N5208	Si-Di	Uni, 70V, 0,075A	31a	Sem,Tix	BA147/100, BA186..190, 1N5606..09,++
1N5209	Si-Di	Uni, 150V, 0,055A	31a	Sem,Tix	BA147/150, BA189..190, 1N5608..07,++
1N521	Si-Di	=1N519: 200V			BY126..127, BY133..134, 1N4003..07,++
1N5210	Si-Di	Uni, 200V, 0,04A	31a		BA147/230, BAY21, BAY88..90,++
1N5211	Si-Di	Gl, 200V, 1A	34a	Rca,Sem,Ssi	BY126..127, BY133..134, 1N4003..07,++
1N5212	Si-Di	=1N5211: 400V	34a		BY126..127, BY133..134, 1N4004..07,++
1N5213	Si-Di	=1N5211: 600V	34a		BY126..127, BY133..134, 1N4005..07,++
1N5214	Si-Di	=1N5211: 800V	34a		BY127, BY133, BY227, 1N4006..07,++
1N5215	Si-Di	=1N5211:	34a(Iso)		→1N5211
1N5216	Si-Di	=1N5212:	34a(Iso)		→1N5212
1N5217	Si-Di	=1N5213:	34a(Iso)		→1N5213
1N5218	Si-Di	=1N5214:	34a(Iso)		→1N5214
1N5219	Si-Di	SS, 30V, <2ns	31a	Msc,Sem	BA218, BAX13, BAX91, 1N4148..49,++
1N522	Si-Di	=1N519: 300V			BY126..127, BY133..134, 1N4004..07,++
1N5220	Si-Di	SS, 30V, <0,7ns	31a	Msc,Sem	—
1N5221	Z-Di	2,4V, 20%, 0,5W	31a	USA,EUR,JAP	BZX55/.., BZX83/.., ZPD.., 1N5985..6031+
1N5221A...5281A	Z-Di	=1N5221..5281: 10%	31a		—
1N5221B...5261B	Z-Di	=1N5221..5281: 5%	31a		—
1N5222	Z-Di	=1N5221: 2,5V	31a		—
1N5223	Z-Di	=1N5221: 2,7V	31a		—
1N5224	Z-Di	=1N5221: 2,8V	31a		—
1N5225	Z-Di	=1N5221: 3,0V	31a		—
1N5226	Z-Di	=1N5221: 3,3V	31a		—
1N5227	Z-Di	=1N5221: 3,6V	31a		—
1N5228	Z-Di	=1N5221: 3,9V	31a		—
1N5229	Z-Di	=1N5221: 4,3V	31a		—
1N523+A5617	Si-Di	=1N519: 400V			BY126..127, BY133..134, 1N4004..07,++
1N5230	Z-Di	=1N5221: 4,7V	31a		—
1N5231	Z-Di	=1N5221: 5,1V	31a		—
1N5232	Z-Di	=1N5221: 5,6V	31a		—
1N5233	Z-Di	=1N5221: 6,0V	31a		—
1N5234	Z-Di	=1N5221: 6,2V	31a		—
1N5235	Z-Di	=1N5221: 6,8V	31a		—
1N5236	Z-Di	=1N5221: 7,5V	31a		—
1N5237	Z-Di	=1N5221: 8,2V	31a		—
1N5238	Z-Di	=1N5221: 8,7V	31a		—
1N5239	Z-Di	=1N5221: 9,1V	31a		—
1N524	Si-Di	=1N519: 600V			BY126..127, BY133..134, 1N4005..07,++

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1N5240	Z-Di	=1N5221: 10V	31a		—
1N5241	Z-Di	=1N5221: 11V	31a		—
1N5242	Z-Di	=1N5221: 12V	31a		—
1N5243	Z-Di	=1N5221: 13V	31a		—
1N5244	Z-Di	=1N5221: 14V	31a		—
1N5245	Z-Di	=1N5221: 15V	31a		—
1N5246	Z-Di	=1N5221: 16V	31a		—
1N5247	Z-Di	=1N5221: 17V	31a		—
1N5248	Z-Di	=1N5221: 18V	31a		—
1N5249	Z-Di	=1N5221: 19V	31a		—
1N525	Si-Di	=1N519: 800V			BY127, BY133, BYW42, 1N4006..07, ++
1N5250	Z-Di	=1N5221: 20V	31a		—
1N5251	Z-Di	=1N5221: 22V	31a		—
1N5252	Z-Di	=1N5221: 24V	31a		—
1N5253	Z-Di	=1N5221: 25V	31a		—
1N5254	Z-Di	=1N5221: 27V	31a		—
1N5255	Z-Di	=1N5221: 28V	31a		—
1N5256	Z-Di	=1N5221: 30V	31a		—
1N5257	Z-Di	=1N5221: 33V	31a		—
1N5256	Z-Di	=1N5221: 36V	31a		—
1N5259	Z-Di	=1N5221: 39V	31a		—
1N526	Si-Di	=1N519: 1000V			BY127, BY133, BYW43, 1N4007, ++
1N5260	Z-Di	=1N5221: 43V	31a		—
1N5261	Z-Di	=1N5221: 47V	31a		—
1N5262	Z-Di	=1N5221: 51V	31a		—
1N5263	Z-Di	=1N5221: 56V	31a		—
1N5264	Z-Di	=1N5221: 60V	31a		—
1N5265	Z-Di	=1N5221: 62V	31a		—
1N5266	Z-Di	=1N5221: 66V	31a		—
1N5267	Z-Di	=1N5221: 75V	31a		—
1N5268	Z-Di	=1N5221: 82V	31a		—
1N5269	Z-Di	=1N5221: 87V	31a		—
1N527	Ge-Di	Uni, 10V	31a	USA	AA112..114, AA116, AA119, 1N60, ++
1N5270	Z-Di	=1N5221: 91V	31a		—
1N5271	Z-Di	=1N5221: 100V	31a		—
1N5272	Z-Di	=1N5221: 110V	31a		—
1N5273	Z-Di	=1N5221: 120V	31a		—
1N5274	Z-Di	=1N5221: 130V	31a		—
1N5275	Z-Di	=1N5221: 140V	31a		—
1N5276	Z-Di	=1N5221: 150V	31a		—
1N5277	Z-Di	=1N5221: 160V	31a		—
1N5278	Z-Di	=1N5221: 170V	31a		—
1N5279	Z-Di	=1N5221: 180V	31a		—
1N5260	Z-Di	=1N5221: 190V	31a		—
1N5281	Z-Di	=1N5221: 200V	31a		—
1N5282(A)	Si-Di	SS, 90V, 0,2A, <4ns	31a	USA	BAW62, BAW78, BAX95, 1N4148..49, ++
1N5283..5314	Si-Di	FED, Strom-Stabi/current regulator	31a	USA, Mot	—
1N52A1	Si-Di	=1N44A1: 15kV		Tos	—
1N53	Si-Di	UHF, Ka-Band-M	Koax	USA	—
1N530	Si-Di	GI, 100V, 0,3A	34a	Sem, Sld, Tix	BA157..159, BY402..405, 1N4002..07, ++
1N531	Si-Di	=1N530: 200V	34a		BA157..159, BY403..405, 1N4003..07, ++
1N5315	Si-Di	SS, 100V, 0,2A, <4ns	31a	Msc, Sem	BAW62, BAW78, BAX95, 1N4148..49, ++
1N5316	Si-Di	SS, 100V, 0,135A, <4ns	31a	Msc, Sem	BAW62, BAW76, BAX95, 1N4148..49, ++
1N5317	Si-Di	SS, 60V, 0,125A, <4ns	31a	Fch, Msc, Sem	BAW62, BAW76, BAX95, 1N4148..49, ++
1N5318	Si-Di	SS, 75V, 0,125A, <4ns	31a	Fch, Msc, Sem	BAW62, BAW76, BAX95, 1N4148..49, ++
1N5319	Si-Di	SS, 40V, 0,1A, <4ns	31a	Fch, Msc, Sem	BAW62, BAW76, BAX95, 1N4148..49, ++
1N532	Si-Di	=1N530: 300V	34a		BA157..159, BY404..405, 1N4004..07, ++
1N5320	Si-Di	S, 120V, 1A, <250ns	31a	USA	BY201/2, BY296..299, BYX58/200, ++
1N5321	Si-Di	Schottky-Di, 30V	31a	Sol	—
1N5322	Si-Di	Schottky-Di, 30V	31a	Sol	—
1N5323	Si-Di	Schottky-Di, 20V	31a	Sol	—
1N5324	Si-Di	kV-GI, 15k, 0,01A	31a	USA	HS10
1N5326	Si-Di	GI, 200V, 12A	31a	Trw	—
1N5329	Si-Di	kV-GI, 6kV, 0,135A	31a	Sem	BYX90, 1N5163
1N533	Si-Di	=1N530: 400V	34a		BA157..159, BY404..405, 1N4004..07, ++
1N5330	Si-Di	GI, 1500V, 0,54A	31a	Sem	BY289, DM513, EM516, GP10W, ++

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1N5331	Si-Di	GI-L, 1200V, 12A(Tc=150°)	32a	USA,Gen	BYW88/1200, 1N4511
1N5332	Si-Di	GI-L, 1200V, 35A(Tc=140°)	32a	USA,Gen	1N4530
1N5333	Z-Di	3,3V, 20%, 5W	31a	USA,Mot,Sie	BZV40/.., BZV48/..
1N5333A...5388A	Z-Di	=1N5333..5388: 10%	31a		—
1N5333B...5388B	Z-Di	=1N5333..5388: 5%	31a		—
1N5334	Z-Di	=1N5333: 3,6V	31a		—
1N5335	Z-Di	=1N5333: 3,9V	31a		—
1N5336	Z-Di	=1N5333: 4,3V	31a		—
1N5337	Z-Di	=1N5333: 4,7V	31a		—
1N5338	Z-Di	=1N5333: 5,1V	31a		—
1N5339	Z-Di	=1N5333: 5,8V	31a		—
1N534	Si-Di	=1N530: 500V	34a		BA158..159, BY405, 1N4005..07,++
1N5340	Z-Di	=1N5333: 6V	31a		—
1N5341	Z-Di	=1N5333: 8,2V	31a		—
1N5342	Z-Di	=1N5333: 6,8V	31a		—
1N5343	Z-Di	=1N5333: 7,5V	31a		—
1N5344	Z-Di	=1N5333: 8,2V	31a		—
1N5345	Z-Di	=1N5333: 8,7V	31a		—
1N5346	Z-Di	=1N5333: 9,1V	31a		—
1N5347	Z-Di	=1N5333: 10V	31a		—
1N5348	Z-Di	=1N5333: 11V	31a		—
1N5349	Z-Di	=1N5333: 12V	31a		—
1N535	Si-Di	=1N530: 800V	34a		BA158..159, BY405, 1N4005..07,++
1N5350	Z-Di	=1N5333: 13V	31a		—
1N5351	Z-Di	=1N5333: 14V	31a		—
1N5352	Z-Di	=1N5333: 15V	31a		—
1N5353	Z-Di	=1N5333: 16V	31a		—
1N5354	Z-Di	=1N5333: 17V	31a		—
1N5355	Z-Di	=1N5333: 18V	31a		—
1N5356	Z-Di	=1N5333: 19V	31a		—
1N5357	Z-Di	=1N5333: 20V	31a		—
1N5358	Z-Di	=1N5333: 22V	31a		—
1N5359	Z-Di	=1N5333: 24V	31a		—
1N538	Si-Di	GI, 50V, 0,75A	34a	Rca,Tix,++	BY126..127, BY133..135, 1N4001..07,++
1N5360	Z-Di	=1N5333: 25V	31a		—
1N5361	Z-Di	=1N5333: 27V	31a		—
1N5362	Z-Di	=1N5333: 28V	31a		—
1N5363	Z-Di	=1N5333: 30V	31a		—
1N5384	Z-Di	=1N5333: 33V	31a		—
1N5365	Z-Di	=1N5333: 38V	31a		—
1N5388	Z-Di	=1N5333: 39V	31a		—
1N5367	Z-Di	=1N5333: 43V	31a		—
1N5388	Z-Di	=1N5333: 47V	31a		—
1N5369	Z-Di	=1N5333: 51V	31a		—
1N537	Si-Di	=1N538: 100V	34a		BY126..127, BY133..135, 1N4002..07,++
1N5370	Z-Di	=1N5333: 58V	31a		—
1N5371	Z-Di	=1N5333: 60V	31a		—
1N5372	Z-Di	=1N5333: 62V	31a		—
1N5373	Z-Di	=1N5333: 68V	31a		—
1N5374	Z-Di	=1N5333: 75V	31a		—
1N5375	Z-Di	=1N5333: 82V	31a		—
1N5376	Z-Di	=1N5333: 87V	31a		—
1N5377	Z-Di	=1N5333: 91V	31a		—
1N5378	Z-Di	=1N5333: 100V	31a		—
1N5379	Z-Di	=1N5333: 110V	31a		—
1N536	Si-Di	=1N536: 200V	34a		BY126..127, BY133..134, 1N4003..07,++
1N5360	Z-Di	=1N5333: 120V	31a		—
1N5381	Z-Di	=1N5333: 130V	31a		—
1N5362	Z-Di	=1N5333: 140V	31a		—
1N5383	Z-Di	=1N5333: 150V	31a		—
1N5384	Z-Di	=1N5333: 160V	31a		—
1N5385	Z-Di	=1N5333: 170V	31a		—
1N5366	Z-Di	=1N5333: 160V	31a		—
1N5387	Z-Di	=1N5333: 190V	31a		—
1N5388	Z-Di	=1N5333: 200V	31a		—
1N5389	Si-Di	kV-GI, 40kV	31a	Edi	—

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1N539	Si-Di	=1N536: 300V	34a		BY126..127, BY133..134, 1N4004..07,++
1N5390	Si-Di	Schottky-Di, 5V	31a	Fch,Tho	—
1N5391(A)	Si-Di	GI, 50V, 1,5A	31a	USA,Mot,Tho	BY251..255, BY226..227, BYW52..56,++
1N5392(A)	Si-Di	=1N5391: 100V	31a		BY251..255, BY226..227, BYW52..56,++
1N5393(A)	Si-Di	=1N5391: 200V	31a		BY251..255, BY226..227, BYW52..56,++
1N5394(A)	Si-Di	=1N5391: 300V	31a		BY252..255, BY226..227, BYW53..56,++
1N5395(A)	Si-Di	=1N5391: 400V	31a		BY252..255, BY226..227, BYW53..56,++
1N5396(A)	Si-Di	=1N5391: 500V	31a		BY253..255, BY226..227, BYW54..56,++
1N5397(A)	Si-Di	=1N5391: 600V	31a		BY253..255, BY226..227, BYW54..56,++
1N5398(A)	Si-Di	=1N5391: 800V	31a		BY254..255, BY227, BYW55..56,++
1N5399(A)	Si-Di	=1N5391: 1000V	31a		BY255, BY227, BYW56, GP15M,++
1N54(A)	Ge-Di	Uni, 75V, 50mA	31a	USA,Nec,Tho	AA113, AA117..118, 1N34
1N540	Si-Di	=1N536: 400V	34a		BY126..127, BY133..134, 1N4004..07,++
1N5400(K)	Si-Di	GI, 50V, 3A	31a	USA,Mot,Tho	BY251..255, BYW17/100, BYW82,++
1N5401(K)	Si-Di	=1N5400: 100V	31a		BY251..255, BYW17/100, BYW82,++
1N5402(K)	Si-Di	=1N5400: 200V	31a		BY251..255, BYW17/200, BYW82,++
1N5403(K)	Si-Di	=1N5400: 300V	31a		BY252..255, BYW17/400, BYW83,++
1N5404(K)	Si-Di	=1N5400: 400V	31a		BY252..255, BYW17/400, BYW83,++
1N5405(K)	Si-Di	=1N5400: 500V	31a		BY253..255, BYW17/600, BYW84,++
1N5406(K)	Si-Di	=1N5400: 600V	31a		BY253..255, BYW17/600, BYW84,++
1N5407(K)	Si-Di	=1N5400: 600V	31a		BY254..255, BYW17/600, BYW85,++
1N5408(K)	Si-Di	=1N5400: 1000V	31a		BY255, BYW17/1000, BYW86,++
1N5409	Si-Di	GI-L, 300V, 40A(Tc=100°)	32a	USA	BYX97/300
1N541	Ge-Di	Dem, h-ohm, 50V, 30mA	31a	USA,Tho	AA113, AA119, 1N34, 1N54, 1N60
1N5410	Si-Di	GI-L, 300V, 12A(Tc=100°)	32a	USA	BYW88/300, BYX78..61, 1N4507..11,++
1N5411	Diac	Ub=29..35V, Ib<0,05mA, Itsm=2A	31l	Rca	1N5761, N413M, BR100, D3202Y, DO201YR
1N5412	Si-Di	SS, 40V, 0,2A, <2ns	31a	Hit,Msc,Sem	BAW62, BAW76, BAX95, 1N4148..49,++
1N5413	Si-Di	SS, 80V, 0,2A, <2ns	31a	Hit,Msc,Sem	BAW62, BAW76, BAX95, 1N4148..49,++
1N5414	Si-Di	SS, 100V, 0,2A, <2ns	31a	Hit,Msc,Sem	BAW62, BAW76, BAX95, 1N4148..49,++
1N5415	Si-Di	GI, 50V, 3A, <150ns	31a	USA,Gia,Tho	BYW16/100, BYW72..78, RGP30A,++
1N5416	Si-Di	=1N5415: 100V	31a		BYW16/100, BYW72..78, RGP30B,++
1N5417	Si-Di	=1N5415: 200V	31a		BYW16/200, BYW72..78, RGP30D,++
1N5418	Si-Di	=1N5415: 400V	31a		BYW16/400, BYW74..78, RGP30G,++
1N5419	Si-Di	=1N5415: 500V, <250ns	31a		BYW16/600, BYW76..78, RGP30K,++
1N542	Ge-Di	=1N541: gep	2x31a		AA113, AA119, 1N34, 1N54, 1N60
1N5420	Si-Di	=1N5415: 600V, <400ns	31a		BYW16/600, BYW76..78, RGP30K,++
1N5421	Si-Di	VHF-Tuning, 200V	31a	Cod,Miv	—
1N5422	Si-Di	VHF-Tuning, 200V	31a	Cod,Miv	—
1N5423	Si-Di	VHF-Tuning, 200V	31a	Cod,Miv	—
1N5424	Si-Di	VHF-Tuning, 100V	31a	Cod,Miv	—
1N5425	Si-Di	VHF-Tuning, 100V	31a	Cod,Miv	—
1N5426	Si-Di	25V		Miv	—
1N5427	Si-Di	SS, RadH, 75V, <4ns	31a	Fch	—
1N5428	Si-Di	S, RadH, 200V, <50ns	31a	Fch	—
1N5429	Si-Di	RadH, 200V	31a	Fch	—
1N543(A)	Si-Di	GI, 1500V, 10..35mA	34a	old	DM513, EM516, RGP01-16, SHG1,5
1N5430	Si-Di	SS, RadH, 75V, <4ns	31a	Fch	—
1N5431	Si-Di	SS, RadH, 80V, <4ns	31a	FCh	—
1N5432	Si-Di	SS, RadH, 20V, <0,75ns	31a	Fch	—
1N5433	Si-Di	GI, S, 720V, 2mA, <400ns	31a	Ssi,Trw	BA156..159, BY204/8, BY203/12,++
1N5434	Si-Di	GI, S, 720V, 2mA, <400ns	31a	Ssi,Trw	BA156..156, BY204/6, BY203/12,++
1N5435	Si-Di	GI/S-L, 720V, 12A(Tc=25°)	31a	Ssi,Trw	—
1N5436	Si-Di	UHF, Ku-Band-M, 16GHz	Koax	Miv,Sld	—
1N5437	Si-Di	UHF, Ku-Band-M, 16GHz	Koax	Miv,Sld	—
1N5438	Si-Di	UHF, Ku-Band-M, 16GHz	Koax	Miv,Sld	—
1N544(A)	Si-Di	GI, 1200V, 15..75mA	34a	old	DM513, EM516, RGP01-16, SHG1,5
1N5441(A...D)	Si-Di	FM/VHF-AFC/Tuning	31a	Mot,Tho,++	—
1N5442(A...D)	Si-Di	FM/VHF-AFC/Tuning	31a	Mot,Tho,++	—
1N5443(A...D)	Si-Di	FM/VHF-AFC/Tuning	31a	Mot,Tho,++	—
1N5444(A...D)	Si-Di	FM/VHF-AFC/Tuning	31a	Mot,Tho,++	—
1N5445(A...D)	Si-Di	FM/VHF-AFC/Tuning	31a	Mot,Tho,++	—
1N5446(A...D)	Si-Di	FM/VHF-AFC/Tuning	31a	Mot,Tho,++	—
1N5447(A...D)	Si-Di	FM/VHF-AFC/Tuning	31a	Mot,Tho,++	—
1N5448(A...D)	Si-Di	FM/VHF-AFC/Tuning	31a	Mot,Tho,++	—
1N5449(A...D)	Si-Di	FM/VHF-AFOTuning	31a	Mot,Tho,++	—
1N5450(A...D)	Si-Di	FM/VHF-AFC/Tuning	31a	Mot,Tho,++	—

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1N5451(A...D)	Si-Di	FM/VHF-AFC/Tuning	31a	Mot,Tho,++	—
1N5452(A...D)	Si-Di	FM/VHF-AFC/Tuning	31a	Mot,Tho,++	—
1N5453(A...D)	Si-Di	FM/VHF-AFC/Tuning	31a	Mot,Tho,++	—
1N5454(A...D)	Si-Di	FM/VHF-AFC/Tuning	31a	Mot,Tho,++	—
1N5455(A...D))	Si-Di	FM/VHF-AFC/Tuning	31a	Mot,Tho,++	—
1N5456(A...D)	Si-Di	FM/VHF-AFC/Tuning	31a	Mot,Tho,++	—
1N5461(A...D)	Si-Di	FM..UHF-AFC/Tuning	31a	Mot,Miv,Tdy	—
1N5462(A...D))	Si-Di	FM..UHF-AFC/Tuning	31a	Mot,Miv,Tdy	—
1N5463(A...D)	Si-Di	FM..UHF-AFC/Tuning	31a	Mot,Miv,Tdy	—
1N5464(A...D)	Si-Di	FM..UHF-AFC/Tuning	31a	Mot,Miv,Tdy	—
1N5465(A...D)	Si-Di	FM..UHF-AFC/Tuning	31a	Mot,Miv,Tdy	—
1N5466(A...D)	Si-Di	FM..UHF-AFC/Tuning	31a	Mot,Miv,Tdy	—
1N5467(A...D)	Si-Di	FM..UHF-AFC/Tuning	31a	Mot,Miv,Tdy	—
1N5468(A...D)	Si-Di	FM..UHF-AFC/Tuning	31a	Mot,Miv,Tdy	—
1N5469(A...D)	Si-Di	FM..UHF-AFC/Tuning	31a	Mot,Miv,Tdy	—
1N547(S)	Si-Di	GI,600V,0,75A	34a	Rca,Tix,++	BY126..127, BY133..134, 1N4005,++
1N5470(A...D)	Si-Di	FM..UHF-AFC/Tuning	31a	Mot,Miv,Tdy	—
1N5471(A...D)	Si-Di	FM..UHF-AFC/Tuning	31a	Mot,Miv,Tdy	—
1N5472(A...D)	Si-Di	FM..UHF-AFC/Tuning	31a	Mot,Miv,Tdy	—
1N5473(A...D)	Si-Di	FM..UHF-AFC/Tuning	31a	Mot,Miv,Tdy	—
1N5474(A...D)	Si-Di	FM..UHF-AFC/Tuning	31a	Mot,Miv,Tdy	—
1N5475(A...D)	Si-Di	FM..UHF-AFC/Tuning	31a	Mot,Miv,Tdy	—
1N5476(A...D)	Si-Di	FM..UHF-AFC/Tuning	31a	Mot,Miv,Tdy	—
1N5477	Si-Di	kV-GI, 6kV,0,6A		USA	—
1N5478	Si-Di	=1N5477: 7,2kV		USA	—
1N5479	Si-Di	=1N5477: 8,4kV		USA	—
1N548	Si-Di	GI, 900V, 0,3A	31a	old	BA159, BY127, BY133, 1N4007,++
1N5480	Si-Di	=1N5477: 9,6kV		USA	—
1N5481	Si-Di	=1N5477: 12kV		USA	—
1N5482	Si-Di	kV-GL, 2,4kV, 1A	31a	USA	—
1N5483	Si-Di	=1N5482: 3,6kV	31a	USA	—
1N5464	Si-Di	=1N5482: 4,8kV	31a	USA	—
1N5485	Si-Di	=1N5482: 6kV	31a	USA	—
1N549	Si-Di	=1N548: 1200V	31a	old	BY127, BY133, BYX95, EM513,++
1N55(A,B)	Ge-Di	Uni, 150..180V, 30..50mA	31a	USA,Tho	—
1N550	Si-Di	GI-L, 100V, 0,5A	32a	Sem,Tix,++	BYX38/300, BYX39/600
1N551	Si-Di	=1N550: 200V	32a		BYX38/300, BYX39/600
1N5510A...5546A	Z-Di	=1N5518..5548: 10%	31a		—
1N5510B...5546B	Z-Di	=1N5518..5546: 5%	31a		—
1N5510C...5546C	Z-Di	=1N5518..5546: 2%	31a		—
1N5510D...5546D	Z-Di	=1N5518..5546: 1%	31a		—
1N5518	Z-Di	3,3V, 20%, 0,4W	31a	USA,Mot	BZX55/.., BZX55/.., ZPD..., 1N5226..57,++
1N5519	Z-Di	=1N5518: 3,6V	31a		—
1N552	Si-Di	=1N550: 300V	32a		BYX38/300, BYX39/600
1N5520	Z-Di	=1N5518: 3,9V	31a		—
1N5521	Z-Di	=1N5518: 4,3V	31a		—
1N5522	Z-Di	=1N5518: 4,7V	31a		—
1N5523	Z-Di	=1N5518: 5,1V	31a		—
1N5524	Z-Di	=1N5518: 5,6V	31e		—
1N5525	Z-Di	=1N5518: 6,2V	31a		—
1N5526	Z-Di	=1N5518: 6,8V	31a		—
1N5527	Z-Di	=1N5518: 7,5V	31a		—
1N5528	Z-Di	=1N5518: 8,2V	31a		—
1N5529	Z-Di	=1N5518: 9,1V	31a		—
1N553	Si-Di	=1N550: 400V	32a		BYX38/600, BYX39/600
1N5530	Z-Di	=1N5518: 10V	31a		—
1N5531	Z-Di	=1N5518: 11V	31a		—
1N5532	Z-Di	=1N5518: 12V	31a		—
1N5533	Z-Di	=1N5518: 13V	31a		—
1N5534	Z-Di	=1N5518: 14V	31a		—
1N5535	Z-Di	=1N5518: 15V	31a		—
1N5536	Z-Di	=1N5518: 16V	31a		—
1N5537	Z-Di	=1N5518: 17V	31a		—
1N5536	Z-Di	=1N5518: 18V	31a		—
1N5539	Z-Di	=1N5518: 19V	31a		—
1N554	Si-Di	=1N550: 500V	32a		BYX38/600, BYX39/600

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1N5540	Z-Di	=1N5518: 20V	31a		—
1N5541	Z-Di	=1N5518: 22V	31a		—
1N5542	Z-Di	=1N5518: 24V	31a		—
1N5543	Z-Di	=1N5518: 25V	31a		—
1N5544	Z-Di	=1N5518: 28V	31a		—
1N5545	Z-Di	=1N5518: 30V	31a		—
1N5546	Z-Di	=1N5518: 33V	31a		—
1N555	Si-Di	=1N550: 600V	32a		BYX33/600, BYX39/600
1N5550	Si-Di	Gl, S, 200V, 3A	31a	USA,Gla	BY251..255, BYW17/200, BYW82..86,++
1N5551	Si-Di	=1N5550: 400V	31a		BY252..255, BYW17/400, BYW83..86,++
1N5552	Si-Di	=1N5550: 600V	31a		BY253..255, BYW17/600, BYW84..86,++
1N5553	Si-Di	=1N5550: 600V	31a		BY254..255, BYW17/600, BYW85..86,++
1N5554	Si-Di	=1N5550: 1000V	31a		BY255, BYW17/1000, BYW86, 1N5408,++
1N5555	Z-Di	TAZ, 33V, 1,5kW(1ms)	34a	USA,Sie	1N5645
1N5556	Z-Di	=1N5555: 43,7V	34a		1N5648
1N5557	Z-Di	=1N5555: 54V	34a		1N5651
1N5558	Z-Di	=1N5555: 191V	34a		1N5664
1N5559	Z-Di	6,8V, 20%, 1W	31a	USA	BZW22/.., BZX61/.., ZPY.., 1N5921..56,++
1N5559A...5594A	Z-Di	=1N5559..5594: 10%	31a		—
1N5559B...5594B	Z-Di	=1N5559+C5695..5594: 5%	31a		—
1N5560	Z-Di	=1N5559: 7,5V	31a		—
1N5561	Z-Di	=1N5559: 8,2V	31a		—
1N5562	Z-Di	=1N5559: 9,1V	31a		—
1N5563	Z-Di	=1N5559: 10V	31a		—
1N5564	Z-Di	=1N5559: 11V	31a		—
1N5565	Z-Di	=1N5559: 12V	31a		—
1N5566	Z-Di	=1N5559: 13V	31a		—
1N5567	Z-Di	=1N5559: 15V	31a		—
1N5568	Z-Di	=1N5559: 16V	31a		—
1N5569	Z-Di	=1N5559: 18V	31a		—
1N5570	Z-Di	=1N5559: 20V	31a		—
1N5571	Z-Di	=1N5559: 22V	31a		—
1N5572	Z-Di	=1N5559: 24V	31a		—
1N5573	Z-Di	=1N5559: 27V	31a		—
1N5574	Z-Di	=1N5559: 30V	31a		—
1N5575	Z-Di	=1N5559: 33V	31a		—
1N5576	Z-Di	=1N5559: 36V	31a		—
1N5577	Z-Di	=1N5559: 39V	31a		—
1N5578	Z-Di	=1N5559: 43V	31a		—
1N5579	Z-Di	=1N5559: 47V	31a		—
1N558	Si-Di	Gl, 1500V, 15mA	34a	Tix	BAY91, RGP01-18,
1N5580	Z-Di	=1N5559: 51V	31a		—
1N5581	Z-Di	=1N5559: 56V	31a		—
1N5582	Z-Di	=1N5559: 62V	31a		—
1N5583	Z-Di	=1N5559: 66V	31a		—
1N5584	Z-Di	=1N5559: 75V	31a		—
1N5585	Z-Di	=1N5559: 62V	31a		—
1N5586	Z-Di	=1N5559: 91V	31a		—
1N5587	Z-Di	=1N5559: 100V	31a		—
1N5588	Z-Di	=1N5559: 110V	31a		—
1N5589	Z-Di	=1N5559: 120V	31a		—
1N5590	Z-Di	=1N5559: 130V	31a		—
1N5591	Z-Di	=1N5559: 150V	31a		—
1N5592	Z-Di	=1N5559: 160V	31a		—
1N5593	Z-Di	=1N5559: 160V	31a		—
1N5594	Z-Di	=1N5559: 200V	31a		—
1N5595	Si-Di	kV-Gl, 5kV, 1,15A		USA	—
1N5596	Si-Di	kV-Gl, 7,5kV, 0,87A		USA	—
1N5597	Si-Di	kV-Gl, 10kV, 0,7A		USA	—
1N5598	Si-Di	kV-Gl, 15kV, 0,47A		USA	—
1N5599	Si-Di	kV-Gl, 2,5kV, 2,1A		USA	—
1N56(A)	Ge-Di	Uni, 50V, 60mA	31a	USA,Tho	AA117..118, AA132..134, 1N60
1N560	Si-Di	Gl, 600V, 0,25A	34a	Sem,Tix,++	BY127, BY133, BYW42, G1K, 1N4006,++
1N5600	Si-Di	kV-Gl, 5kV, 1,4A		USA	—
1N5601	Si-Di	kV-Gl, 7,5kV, 0,92A		USA	—
1N5602	Si-Di	kV-Gl, 2,5kV, 4,6A		USA	—

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1N5603	Si-Di	kV-Gl, 5kV, 3,5A		USA	—
1N5604	Si-Di	kV-Gl, 7,5kV, 2,3A		USA	—
1N5605	Si-Di	Uni, 70V	31a	USA, Itt	BA188..190, BAY19..21, BAY45..46, ++
1N5606	Si-Di	Uni, 150V, 0,1A	31a	USA, Itt	BA189..190, BAY20..21, BAY45..46, ++
1N5607	Si-Di	Uni, 200V, 0,15A	31a	USA, Itt	BA190, BAW52, BAY21, BAY46, ++
1N5606	Si-Di	S, 120V, 0,15A, <300ns	31a	USA, Hit, Itt	BA157..159, BAV19..21, BAX15..17, ++
1N5609	Si-Di	S, 120V, 0,15A, <300ns	31a	USA, Hit, Itt	BA157..159, BAV19..21, BAX15..17, ++
1N561	Si-Di	=1N560: 1000V	34a		BY127, BY133, BYW43, G1M, 1N4007, ++
1N5610	Z-Di	=1N5555:	31a	Uni	→1N5555
1N5611	Z-Di	=1N5556:	31a	Uni	→1N5556
1N5612	Z-Di	=1N5557:	31a	Uni	→1N5557
1N5613	Z-Di	=1N5558:	31a		→1N5558
1N5614	Si-Di	Gl, 200V, 1A	31a	USA, Sie, Tho	BY126..127, BY133..134, 1N4003..07, ++
1N5615	Si-Di	Gl, S, 200V, 1A, <150ns	31a	USA, Sie, Tho	BY201/2, BYT52D, BYX92/200, ++
1N5616	Si-Di	=1N5614: 400V	31a		BY126..127, BY133..134, 1N4004..07, ++
1N5617	Si-Di	=1N5615: 400V	31a		BY201/4, BYT52G, BYX92/400, ++
1N5618	Si-Di	=1N5614: 600V	31a		BY126..127, BY133..134, 1N4005..07, ++
1N5619	Si-Di	=1N5615: 600V	31a		BY201/6, BYT52J, RGP10J, ++
1N562	Si-Di	Gl-L, 600V, 0,4A	32a	USA	BYX38/900, BYX39/600
1N5620	Si-Di	=1N5614: 600V	31a		BY127, BY133, BY227, 1N4006..07, ++
1N5620P1..5665P1+A5747	Z-Di	=1N5629..5665:	31a		—
1N5621	Si-Di	=1N5615: 800V	31a		BYV15..16, BYT52K, RGP10K, ++
1N5622	Si-Di	=1N5614: 1000V	31a		BY127, BY133, BY227, 1N4007, ++
1N5623	Si-Di	=1N5615: 1000V	31a		BYV16, BYV36E, BYT52M, RGP10M, ++
1N5624(GP)	Si-Di	Gl, 200V, 5A	31a	USA, EUR, Nec	BY500/200, MR752..760, MR822..826
1N5625(GP)	Si-Di	=1N5624: 400V	31a		BY500/400, MR754..760, MR824..826
1N5626(GP)	Si-Di	=1N5524: 600V	31a		BY500/600, MR756..760, MR826
1N5627(GP)	Si-Di	=1N5624: 800V	31a		BY214/800, MR758..760
1N5628	Si-Di	kV-Gl, 3kV, 0,5A		Gen	—
1N5629(A)	Z-Di	TAZ, 6,8V, 1,5kW(1ms)	34a	USA, Sie, Tho	1N6267..6303, (1N6036..72, 1N6136..73)
1N563	Si-Di	=1N562: 1000V	32a		BYX38/1200, BYX39/1000
1N5630(A)	Z-Di	=1N5629: 7,5V	34a		—
1N5631(A)	Z-Di	=1N5629: 6,2V	34a		—
1N5632(A)	Z-Di	=1N5629: 9,1V	34a		—
1N5633(A)	Z-Di	=1N5629: 10V	34a		—
1N5634(A)	Z-Di	=1N5629: 11V	34a		—
1N5635(A)	Z-Di	=1N5629: 12V	34a		—
1N5636(A)	Z-Di	=1N5629: 13V	34a		—
1N5637(A)	Z-Di	=1N5629: 15V	34a		—
1N5638(A)	Z-Di	=1N5629: 16V	34a		—
1N5639(A)	Z-Di	=1N5629: 16V	34a		—
1N5640(A)	Z-Di	=1N5629: 20V	34a		—
1N5641(A)	Z-Di	=1N5629: 22V	34a		—
1N5642(A)	Z-Di	=1N5629: 24V	34a		—
1N5643(A)	Z-Di	=1N5629: 27V	34a		—
1N5644(A)	Z-Di	=1N5629: 30V	34a		—
1N5645(A)	Z-Di	=1N5629: 33V	34a		—
1N5646(A)	Z-Di	=1N5629: 36V	34a		—
1N5647(A)	Z-Di	=1N5629: 39V	34a		—
1N5648(A)	Z-Di	=1N5629: 43V	34a		—
1N5649(A)	Z-Di	=1N5629: 47V	34a		—
1N5650(A)	Z-Di	=1N5629: 51V	34a		—
1N5651(A)	Z-Di	=1N5629: 56V	34a		—
1N5652(A)	Z-Di	=1N5629: 62V	34a		—
1N5653(A)	Z-Di	=1N5629: 68V	34a		—
1N5654(A)	Z-Di	=1N5629: 75V	34a		—
1N5655(A)	Z-Di	=1N5629: 82V	34a		—
1N5656(A)	Z-Di	=1N5629: 91V	34a		—
1N5657(A)	Z-Di	=1N5629: 100V	34a		—
1N5656(A)	Z-Di	=1N5629: 110V	34a		—
1N5659(A)	Z-Di	=1N5629: 120V	34a		—
1N566	Ge-Di	Uni, 275V	31a	Idc	—
1N5660(A)	Z-Di	=1N5629: 130V	34a		—
1N5661(A)	Z-Di	=1N5629: 150V	34a		—
1N5662(A)	Z-Di	=1N5629: 160V	34a		—
1N5663(A)	Z-Di	=1N5629: 170V	34a		—

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1N5664(A)	Z-Di	=1N5629: 180V	34a		—
1N5665(A)	Z-Di	=1N5629: 200V	34a		—
1N5666	Z-Di	1,6V, 20%, 0,25W	31	Sie, Sty	BZX55/.., BZX79/.., ZPD.., 1N5221..32,++
1N5666A...5678A	Z-Di	=1N5666..5678: 10%	31		—
1N5667	Z-Di	=1N5666: 1,8V	31		—
1N5666	Z-Di	=1N5666: 2V	31		—
1N5669	Z-Di	=1N5666: 2,2V	31		—
1N567	Ge-Di	S, 125V, 300ns	31a	Idc, Sem	—
1N5670	Z-Di	=1N5666: 2,5V	31		—
1N5671	Z-Di	=1N5666: 2,8V	31		—
1N5672	Z-Di	=1N5666: 3,1V	31		—
1N5673	Z-Di	=1N5666: 3,4V	31		—
1N5674	Z-Di	=1N5666: 3,7V	31		—
1N5675	Z-Di	=1N5666: 4,1V	31		—
1N5676	Z-Di	=1N5666: 4,5V	31		—
1N5677	Z-Di	=1N5666: 4,9V	31		—
1N5678	Z-Di	=1N5666: 5,4V	31		—
1N5679	Si-Di	Gl, 50V, 1A	31a	Gie	BY126..127, BY133..135, 1N4001..07,++
1N566	Ge-Di	S, 50V, 80ns	31a	Idc, Itt, Sem	—
1N5680	Si-Di	=1N5679: 100V	31a		BY126..127, BY133..135, 1N4001..07,++
1N5661(A,B)	Si-Di	VHF-Tuning	31a	Cod, Trw	—
1N5682(A,B)	Si-Di	VHF-Tuning	31a	Cod, Trw	—
1N5683(A,B)	Si-Di	VHF-Tuning	31a	Cod, Trw	—
1N5684(A,B)	Si-Di	VHF-Tuning	31a	Cod, Trw	—
1N5685(A,B)	Si-Di	VHF-Tuning	31a	Cod, Trw	—
1N5686(A,B)	Si-Di	VHF-Tuning	31a	Cod, Trw	—
1N5687(A,B)	Si-Di	VHF-Tuning	31a	Cod, Trw	—
1N5688(A,B)	Si-Di	VHF-Tuning	31a	Cod, Trw	—
1N5689(A,B)	Si-Di	VHF-Tuning	31a	Cod, Trw	—
1N569	Ge-Di	Uni, 25V	31a	Idc, Itt, Sem	AA139, 1N270
1N5690(A,B)	Si-Di	VHF-Tuning	31a	Cod, Trw	—
1N5691(A,B)	Si-Di	VHF-Tuning	31a	Cod, Trw	—
1N5692(A,B)	Si-Di	VHF-Tuning	31a	Cod, Trw	—
1N5693(A,B)	Si-Di	VHF-Tuning	31a	Cod, Trw	—
1N5694(A,B)	Si-Di	VHF-Tuning	31a	Cod, Trw	—
1N5695(A,B)	Si-Di	VHF-Tuning	31a	Cod, Trw	—
1N5696(A,B)	Si-Di	VHF-Tuning	31a	Cod, Trw	—
1N5697(A,B)	Si-Di	VHF-Tuning	31a	Cod, Trw	—
1N5698(A,B)	Si-Di	VHF-Tuning	31a	Cod, Trw	—
1N5699(A,B)	Si-Di	VHF-Tuning	31a	Cod, Trw	—
1N57(A)	Ge-Di	Uni, 80V, 40mA	31a	USA, Tho	AA117..118, AA132..133
1N570	Si-Di	Gl, 1500V, 0,75A		USA	—
1N5700(A,B)	Si-Di	VHF-Tuning	31a	Cod, Trw	—
1N5701(A,B)	Si-Di	VHF-Tuning	31a	Cod, Trw	—
1N5702(A,B)	Si-Di	VHF-Tuning	31a	Cod, Trw	—
1N5703(A,B)	Si-Di	VHF-Tuning	31a	Cod, Trw	—
1N5704(A,B)	Si-Di	VHF-Tuning	31a	Cod, Trw	—
1N5705(A,B)	Si-Di	VHF-Tuning	31a	Cod, Trw	—
1N5706(A,B)	Si-Di	VHF-Tuning	31a	Cod, Trw	—
1N5707(A,B)	Si-Di	VHF-Tuning	31a	Cod, Trw	—
1N5706(A,B)	Si-Di	VHF-Tuning	31a	Cod, Trw	—
1N5709(A,B)	Si-Di	VHF-Tuning	31a	Cod, Trw	—
1N571	Ge-Di	S, 15V, <4µs	34a	USA, Itt	—
1N5710(A,B)	Si-Di	VHF-Tuning	31a	Cod, Trw	—
1N5711	Si-Di	Schottky, VHF/UHF-Dem, 70V, 15mA	31a	USA, Tho	BAR28, HSS102
1N5712	Si-Di	Schottky, VHF/UHF-Dem, 20V, 35mA	31a	USA, Tho	BAR10, 1S1992, 1SS101, 1SS109
1N5713	Si-Di	Schottky, 12V	31a	USA	—
1N5714	Si-Di	VHF-Tuning, 200V	31a	Tdy	—
1N5715	Si-Di	VHF-Tuning, 200V	31a	Tdy	—
1N5716	Si-Di	VHF-Tuning, 200V	31a	Tdy	—
1N5717	Si-Di	VHF-Tuning, 100V	31a	Tdy	—
1N5716	Si-Di	VHF-Tuning, 100V	31a	Tdy	—
1N5719	Si-Di	Uni, 100V	31a	Hew, Mic	BA166..190, BA147/100, 1N5606..09,++
1N5720	Si-Di	S, 30V, <10ns	31a	Itt, Hit	BA317, BAW53, BAY71, 1N4148..49,++
1N5721	Si-Di	=1N5720: 15V	31a	Itt, Hit	BA317, BAW53, BAY71, 1N4148..49,++
1N5726	Si-Di	S, 80V, <10ns	31a	Itt, Hit	BAV14, BAW26..27

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1N5727	Si-Di	=1N5726: 50V	31a	Itt,Hit	BAV14, BAW24..27
1N5726	Z-Di	4,7V, 0,4W	31a	USA,Phi,Sie	BZX55/, BZX79/, ZPD.., 1N5230..67,++
1N5728A...5757A	Z-Di	=1N5728..5757: 5%	31a		—
1N5728B...5757B	Z-Di	=1N5728..5757: 2%	31a		—
1N5728C...5757C	Z-Di	=1N5728..5757: 1%	31a		—
1N5729	Z-Di	=1N5728: 5,1V	31a		—
1N573	Ge-Di	Gl, 380V, 0,25A			—
1N5730	Z-Di	=1N5728: 5,6V	31a		—
1N5731	Z-Di	=1N5726: 6,2V	31a		—
1N5732	Z-Di	=1N5728: 6,8V	31a		—
1N5733	Z-Di	=1N5728: 7,5V	31a		—
1N5734	Z-Di	=1N5728: 8,2V	31a		—
1N5735	Z-Di	=1N5726: 9,1V	31a		—
1N5736	Z-Di	=1N5728: 10V	31a		—
1N5737	Z-Di	=1N5728: 11V	31a		—
1N5736	Z-Di	=1N5728: 12V	31a		—
1N5739	Z-Di	=1N5728: 13V	31a		—
1N574	Ge-Di	Gl, 380V, 0,3A			—
1N5740	Z-Di	=1N5728: 15V	31a		—
1N5741	Z-Di	=1N5728: 16V	31a		—
1N5742	Z-Di	=1N5728: 18V	31a		—
1N5743	Z-Di	=1N5728: 20V	31a		—
1N5744	Z-Di	=1N5728: 22V	31a		—
1N5745	Z-Di	=1N5728: 24V			—
1N5746	Z-Di	=1N5728: 27V	31a		—
1N5747	Z-Di	=1N5728: 30V	31a		—
1N5746	Z-Di	=1N5726: 33V	31a		—
1N5749	Z-Di	=1N5728: 36V	31a		—
1N575(A)	Ge-Di	Gl, 380V, 0,35A			—
1N5750	Z-Di	=1N5728: 39V	31a		—
1N5751	Z-Di	=1N5728: 43V	31a		—
1N5752	Z-Di	=1N5728: 47V	31a		—
1N5753	Z-Di	=1N5728: 51V	31a		—
1N5754	Z-Di	=1N5726: 56V	31a		—
1N5755	Z-Di	=1N5728: 62V	31a		—
1N5756	Z-Di	=1N5728: 68V	31a		—
1N5757	Z-Di	=1N5726: 75V	31a		—
1N5756	Diac	Ub=16..24V, Ib<0,1mA, Itsm=2A	7l	Mot	—
1N5758A	Diac	Ub=18..22V, Ib<0,025mA, Itsm=2A	7l	Mot	—
1N5759	Diac	Ub=20..28V, Ib<0,1mA, Itsm=2A	7l	Mot	—
1N5759A	Diac	Ub=22..26V, Ib<0,025mA, Itsm=2A	7l	Mot	—
1N576(A)	Ge-Di	Gl, 380V, 0,4A			—
1N5760	Diac	Ub=24..32V, Ib<0,1mA, Itsm=2A	7l	Mot	N413L, D3202U
1N5760A	Diac	Ub=26..30V, Ib<0,025mA, Itsm=2A	7l	Mot	(N413L, D3202U)
1N5761	Diac	Ub=28..36V, Ib<0,1mA, Itsm=2A	7l	Mot	N413M, BR100, D3202Y, DO201YR
1N5761A	Diac	Ub=30..34V, Ib<0,025mA, Itsm=2A	7l	Mot	(N413+F5888M, BR100, D3202Y, DO201YR)
1N5762	Diac	Ub=32..40V, Ib<0,1mA, Itsm=2A	7l	Mot	N413N, D3202U
1N5782A	Diac	Ub=34..38V, Ib<0,025mA, Itsm=2A	7l	Mot	(N413N, D3202U)
1N5763	Si-Di	Gl-L, 26V, 300A(Tc=100°)		Del	—
1N5764	GaAs-Di	UHF, Ku-Band-M	Koax	Miv	—
1N5766	Si-Di	Gl, S, 110V, 400ns	32a	Sol	1N4525..4530
1N5767	PIN-Di	Uni, 100V, <0,4pF(50V)	31a	Uni	—
1N5766	Si-Di	8-Di Logik-Gatter/logic gate	10-FLP	Fch	—
1N5770	Si-Di	8-Di Logik-Gatter/logic gate	10-FLP	Fch	—
1N5772	Si-Di	16-Di Logik-Gafter/logic gata	10-FLP	Fch	—
1N5774	Si-Di	16-Di-Logik-Gafter/logic gate	14-FLP	Fch	—
1N5779	Trigger-Di	=1N5156: Ub=11..13V	31a	Mot	—
1N5760	Trigger-Di	=1N5158: Ub=12..14V	31a	Mot	—
1N5781	Triggar-Di	=1N5156: Ub=13..15V	31a	Mot	—
1N5782	Trigger-Di	=1N5156: Ub=8..10V, Ib<0,1mA	31a	Mot	—
1N5783	Trigger-Di	=1N5156: Ub=9..11V, Ib<0,1mA	31a	Mot	—
1N5784	Trigger-Di	=1N5156: Ub=10..12V, Ib<0,1mA	31a	Mot	—
1N5785	Trigger-Di	=1N5156: Ub=11..13V, Ib<0,1mA	31a	Mot	—
1N5766	Trigger-Di	=1N5156: Ub=12..14V, Ib<0,1mA	31a	Mot	—
1N5787	Trigger-Di	=1N5156: Ub=13..15V, Ib<0,1mA	31a	Mot	—
1N5788	Trigger-Di	=1N5156: Ub=8..10V, Ib<0,1mA	31a	Mot	—

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1N5789	Trigger-Di	=1N5158: Ub=9..11V, Ib<0,1mA	31a	Mot	—
1N5790	Trigger-Di	=1N5158: Ub=10..12V, Ib<0,1mA	31a	Mot	—
1N5791	Trigger-Di	=1N5158: Ub=11..13V, Ib<0,1mA	31a	Mot	—
1N5792	Trigger-Di	=1N5158: Ub=12..14V, Ib<0,1mA	31a	Mot	—
1N5793	Trigger-Di	=1N5158: Ub=13..15V, Ib<0,1mA	31a	Mot	—
1N5794	Si-Di	GL, 50V, 1A	31a	Fch	BY 126..127, BY 133..135, 1N4001..07,++
1N5795	Si-Di	=1N5794: 100V	31a		BY 126..127, BY 133..135, 1N4002..07,++
1N5796	Si-Di	=1N5794: 200V	31a		BY 128..127, BY 133..134, 1N4003..07,++
1N5797	Si-Di	=1N5794: 400V	31a		BY 128..127, BY 133..134, 1N4004..07,++
1N5798	Si-Di	=1N5794: 600V	31a		BY 126..127, BY 133..134, 1N4005..07,++
1N5799	Si-Di	=1N5794: 600V	31a		BY 127, BY 133, BY 227, 1N4006..07,++
1N58(A)	Ge-Di	Uni, 115V, 50mA	31a	USA,Nec,Tho	AA 117..118, AA 132..133
1N5800	Si-Di	=1N5794: 1000V	31a		BY 127, BY 133, BY 227, 1N4007,++
1N5802	Si-Di	Gl, S, 50V, 2,5A, <25ns	31a	USA,Gie	BYV 28/50, EGP 30A, FE 3A
1N5803	Si-Di	=1N5802: 75V	31a		BYV 28/100, EGP 30B, FE 3B
1N5804	Si-Di	=1N5802: 100V	31a		BYV 28/100, EGP 30B, FE 3B
1N5805	Si-Di	=1N5802: 125V	31a		BYV 28/150, EGP 30C, FE 3C
1N5806	Si-Di	=1N5802: 150V	31a		BYV 28/150, EGP 30C, FE 3C
1N5807	Si-Di	Gl, S, 50V, 6A, <30ns	31a	USA,Gie	BYV 61..83, FE 6A
1N5808	Si-Di	=1N5807: 75V	31a		BYV 62..63, FE 6B
1N5809	Si-Di	=1N5807: 100V	31a		BYV 62..83, FE 6B
1N581	Ge-Di	Gl, 380V, 0,25A		Gen	—
1N5810	Si-Di	=1N5807: 125V	31a		BYV 83, FE 6C
1N5811	Si-Di	=1N5807: 150V	31a		BYV 63, FE 8C
1N5812	Si-Di	Gl/S-L, 50V, 20A, <25ns	32a	USA,Gie	BYW 77/50
1N5813	Si-Di	=1N5812: 75V	32a		BYW 77/100
1N5814	Si-Di	=1N5812: 100V	32a		BYW 77/100
1N5815	Si-Di	=1N5812: 125V	32a		BYW 77/150
1N5816	Si-Di	=1N5812: 150V	32a		BYW 77/150
1N5817	Si-Di	Schottky-Gl, 20V, 1A	31a	Gie,Mot,Phi	BYS 21, BYV 10-20, SB 120
1N5817	Si-Di			Itt,Tho	—
1N5818	Si-Di	=1N5817: 30V	31a		BYS 21, BYV 10-30, SB 130
1N5819	Si-Di	=1N5817: 40V	31a		BYS 21, BYV 10-40, SB 140
1N582	Ge-Di	Gl, 380V, 0,3A		Gen	—
1N5820	Si-Di	Schottky-Gl, 20V, 3A	31a	Gie,Mot	BYS 26, MBR 320, SB 320
1N5821	Si-Di	=1N5820: 30V	31a		BYS 26, MBR 330, SB 330
1N5822	Si-Di	=1N5820: 40V	31a	Gie,Mot	BYS 26, MBR 340, SB 340, HRP 24
1N5823	Si-Di	Schottky-GL, 20V, 5A	34a	Mot	BYS 06, SB 520
1N5824	Si-Di	=1N5823: 30V	34a		BYS 06, SB 530
1N5825	Si-Di	=1N5823: 40V	34a		BYS 06, SB 540
1N5826	Si-Di	Schottky-Gl-L, 20V, 15A(Tc=85°)	32a	Mot	BYS 15, MBR 1520
1N5827	Si-Di	=1N5826: 30V	32a		BYS 15, MBR 1530
1N5828	Si-Di	=1N5826: 40V	32a		BYS 15, MBR 1540
1N5829	Si-Di	Schottky-Gl-L, 20V, 25A(Tc=85°)	32a	Mot	BYS 30..32, BYS 35/20, MBR 2520
1N583	Ge-Di	Gl, 350V, 0,35A		Gen	—
1N5830	Si-Di	=1N5829: 30V	32a		BYS 30..32, BYS 35/30, MBR 2530
1N5831	Si-Di	=1N5829: 40V	32a		BYS 30..32, BYS 35/40, MBR 2540
1N5832	Si-Di	Schottky-Gl-L, 20V, 40A(Tc=75°)	32a	Mot	BYS 50..51, BYS 60/20, MBR 4020
1N5833	Si-Di	=1N5832: 30V	32a		BYS 50..51, BYS 60/3+F61740, MBR 4030
1N5834	Si-Di	=1N5832: 40V	32a		BYS 50..51, BYS 60/40, MBR 4040
1N5835	Si-Di	Gl, S, 30V, 3A, <100ns	31a	Cri	BYV 28/50, EGP 30A, FE 3A
1N5836	Si-Di	=1N5835: 50V	31a		BYV 28/50, EGP 30A, FE 3A
1N5837	Z-Di	2,4V, 20%, 0,5W	7d	Fer,Mot,Spr	BZX55/.., BZX83/.., ZPD.., 1N5221..81,++
1N5837A..5897A	Z-Di	=1N5837..5897: 10%	7d		—
1N5837B..5897B	Z-Di	=1N5837..5897: 5%	7d		—
1N5837C..5897C	Z-Di	=1N5837..5897: 2%	7d		—
1N5837D..5897D	Z-Di	=1N5837..5897: 1%	7d		—
1N5838	Z-Di	=1N5837: 2,5V	7d		—
1N5839	Z-Di	=1N5837: 2,7V	7d		—
1N584	Ge-Di	Gl, 380V, 0,4A		Gen	—
1N5840	Z-Di	=1N5837: 2,8V	7d		—
1N5841	Z-Di	=1N5837: 3V	7d		—
1N5842	Z-Di	=1N5837: 3,3V	7d		—
1N5843	Z-Di	=1N5837: 3,6V	7d		—
1N5844	Z-Di	=1N5837: 3,9V	7d		—
1N5845	Z-Di	=1N5837: 4,3V	7d		—

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1N5846	Z-Di	=1N5837: 4,7V	7d		—
1N5847	Z-Di	=1N5837: 5,1V	7d		—
1N5846	Z-Di	=1N5837: 5,6V	7d		—
1N5849	Z-Di	=1N5837: 6V	7d		—
1N5850	Z-Di	=1N5837: 6,2V	7d		—
1N5851	Z-Di	=1N5837: 6,8V	7d		—
1N5852	Z-Di	=1N5837: 7,5V	7d		—
1N5853	Z-Di	=1N5837: 8,2V	7d		—
1N5854	Z-Di	=1N5837: 8,7V	7d		—
1N5855	Z-Di	=1N5837: 9,1V	7d		—
1N5858	Z-Di	=1N5837: 10V	7d		—
1N5857	Z-Di	=1N5837: 11V	7d		—
1N5858	Z-Di	=1N5837: 12V	7d		—
1N5859	Z-Di	=1N5837: 13V	7d		—
1N5860	Z-Di	=1N5837: 14V	7d		—
1N5861	Z-Di	=1N5837: 15V	7d		—
1N5862	Z-Di	=1N5837: 16V	7d		—
1N5868	Z-Di	=1N5837: 17V	7d		—
1N5864	Z-Di	=1N5837: 18V	7d		—
1N5865	Z-Di	=1N5837: 19V	7d		—
1N5866	Z-Di	=1N5837: 20V	7d		—
1N5867	Z-Di	=1N5837: 22V	7d		—
1N5868	Z-Di	=1N5837: 24V	7d		—
1N5869	Z-Di	=1N5837: 25V	7d		—
1N5870	Z-Di	=1N5837: 27V	7d		—
1N5671	Z-Di	=1N5837: 28V	7d		—
1N5872	Z-Di	=1N5837: 30V	7d		—
1N5873	Z-Di	=1N5837: 33V	7d		—
1N5874	Z-Di	=1N5837: 36V	7d		—
1N5875	Z-Di	=1N5837: 39V	7d		—
1N5876	Z-Di	=1N5837: 43V	7d		—
1N5877	Z-Di	=1N5837: 47V	7d		—
1N5878	Z-Di	=1N5837: 51V	7d		—
1N5879	Z-Di	=1N5837: 58V	7d		—
1N588	Si-Di	GL, 1500V, 0,1A	34a	USA	BAY91, RGP01-16
1N5860	Z-Di	=1N5837: 60V	7d		—
1N5881	Z-Di	=1N5837: 62V	7d		—
1N5862	Z-Di	=1N5837: 68V	7d		—
1N5883	Z-Di	=1N5837: 75V	7d		—
1N5884	Z-Di	=1N5837: 82V	7d		—
1N5885	Z-Di	=1N5837: 87V	7d		—
1N5886	Z-Di	=1N5837: 91V	7d		—
1N5887	Z-Di	=1N5837: 100V	7d		—
1N5886	Z-Di	=1N5837: 110V	7d		—
1N5889	Z-Di	=1N5837: 120V	7d		—
1N589	Si-Di	GL, 1500V, 0,25A	34a	USA	BAY91, DM513, EM516, GP10Y
1N5890	Z-Di	=1N5837: 130V	7d		—
1N5891	Z-Di	=1N5837: 140V	7d		—
1N5892	Z-Di	=1N5837: 150V	7d		—
1N5893	Z-Di	=1N5837: 160V	7d		—
1N5894	Z-Di	=1N5837: 170V	7d		—
1N5895	Z-Di	=1N5837: 160V	7d		—
1N5896	Z-Di	=1N5837: 190V	7d		—
1N5897	Z-Di	=1N5837: 200V	7d		—
1N5896	8I-Di	Gl, S, 50V, 3A		Gie	BY251..255, BYW17/100, 1N5400..08, ++
1N5899	Si-Di	=1N5898: 100V			BY251..255, BYW17/100, 1N5401..08, ++
1N59	Ge-Di	Uni, 260V, 50mA	31a	Idc	—
1N590	Si-Di	GL, 1500V, 25mA	=34a	Ssl	BAY91, RGP01-16
1N5900	Si-Di	=1N5898: 200V			BY251..255, BYW17/200, 1N5402..08, ++
1N5901	Si-Di	=1N5898: 400V			BY252..255, BYW17/400, 1N5404..08, ++
1N5902	Si-Di	=1N5898: 600V			BY258..255, BYW17/600, 1N5406..08, ++
1N5903	Si-Di	=1N5898: 800V			BY254..255, BYW17/800, 1N5407..08, ++
1N5904	Si-Di	=1N5898: 1000V			BY255, BYW17/1000, 1N5408, ++
1N5905	Si-Di	=1N5896: 1200V			BY255, BY436, BYW17/1200
1N5906	Si-Di	UHF, Ku-Band-M, 18GHz	Koax	Miv	—
1N5907	Z-Di	=1N5629: 6...7V	34a	Scn, Sie, Tho	—

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1N5908	Z-Di	=1N5629: 6...7V	31a		—
1N5909..5912	Opto				—
1N591	Si-Di	=1N590:	~34b		BAY91, RGP01-16
1N5913	Z-Di	3,3V, 20%, 1,5W(Tc=75°)	31a	USA,Mot,Sie	BZW22/.., BZX61/.., ZPY.., BZY97/..
1N5913A...5956A	Z-Di	=1N5913..5956: 10%	31a		—
1N5913B...5956B	Z-Di	=1N5913..5956: 5%	31a		—
1N5913C...5956C	Z-Di	=1N5913..5956: 2%	31a		—
1N5913D...5956D	Z-Di	=1N5913..5956: 1%	31a		—
1N5914	Z-Di	=1N5913: 3,6V	31a		—
1N5915	Z-Di	=1N5913: 3,9V	31a		—
1N5916	Z-Di	=1N5913: 4,3V	31a		—
1N5917	Z-Di	=1N5913: 4,7V	31a		—
1N5918	Z-Di	=1N5913: 5,1V	31a		—
1N5919	Z-Di	=1N5913: 5,6V	31a		—
1N5920	Z-Di	=1N5913: 6,2V	31a		—
1N5921	Z-Di	=1N5913: 6,8V	31a		—
1N5922	Z-Di	=1N5913: 7,5V	31a		—
1N5923	Z-Di	=1N5913: 8,2V	31a		—
1N5924	Z-Di	=1N5913: 9,1V	31a		—
1N5925	Z-Di	=1N5913: 10V	31a		—
1N5926	Z-Di	=1N5913: 11V	31a		—
1N5927	Z-Di	=1N5913: 12V	31a		—
1N5928	Z-Di	=1N5913: 13V	31a		—
1N5929	Z-Di	=1N5913: 15V	31a		—
1N5930	Z-Di	=1N5913: 16V	31a		—
1N5931	Z-Di	=1N5913: 18V	31a		—
1N5932	Z-Di	=1N5913: 20V	31a		—
1N5933	Z-Di	=1N5913: 22V	31a		—
1N5934	Z-Di	=1N5913: 24V	31a		—
1N5935	Z-Di	=1N5913: 27V	31a		—
1N5936	Z-Di	=1N5913: 30V	31a		—
1N5937	Z-Di	=1N5913: 33V	31a		—
1N5938	Z-Di	=1N5913: 36V	31a		—
1N5939	Z-Di	=1N5913: 39V	31a		—
1N5940	Z-Di	=1N5913: 43V	31a		—
1N5941	Z-Di	=1N5913: 47V	31a		—
1N5942	Z-Di	=1N5913: 51V	31a		—
1N5943	Z-Di	=1N5913: 56V	31a		—
1N5944	Z-Di	=1N5913: 62V	31a		—
1N5945	Z-Di	=1N5913: 68V	31a		—
1N5946	Z-Di	=1N5913: 75V	31a		—
1N5947	Z-Di	=1N5913: 82V	31a		—
1N5948	Z-Di	=1N5913: 91V	31a		—
1N5949	Z-Di	=1N5913: 100V	31a		—
1N5950	Z-Di	=1N5913: 110V	31a		—
1N5951	Z-Di	=1N5913: 120V	31a		—
1N5952	Z-Di	=1N5913: 130V	31a		—
1N5953	Z-Di	=1N5913: 150V	31a		—
1N5954	Z-Di	=1N5913: 160V	31a		—
1N5955	Z-Di	=1N5913: 180V	31a		—
1N5956	Z-Di	=1N5913: 200V	31a		—
1N5957	PIN-Di	100V, <0,4pF(50V)	31a	Uni	—
1N596	Si-Di	Gl, 600V, 0,15A	34a	USA	BA156..159, BAY89..90, BY207
1N5963	Z-Di	5,6V, 5%, 5W	31a	Uni	BZV40/C5V6, BZV48/C5V6, 2N5339B
1N5964	Z-Di	6,2V, 5%, 5W	31a	Uni	BZV40/C6V2, BZV48/C6V2, 2N5341B
1N597	Si-Di	=1N596: 800V	34a		BA159, BAY90, BY204/8
1N598	Si-Di	=1N596: 1000V	34a		BA159, BAY90, BY204/10
1N5965	Z-Di	2,4V, 20%, 0,5W	31a	USA,Mot,Sie	BZX55/.., BZX63/.., ZPD.., 1N5221..61,..
1N5965A...6031A	Z-Di	=1N5965..6031: 10%	31a		—
1N5965B...6031B	Z-Di	=1N5965..6031: 5%	31a		—
1N5965C...6031C	Z-Di	=1N5965..6031: 2%	31a		—
1N5965D...6031D	Z-Di	=1N5965..6031: 1%	31a		—
1N5966	Z-Di	=1N5965: 2,7V	31a		—
1N5967	Z-Di	=1N5965: 3V	31a		—
1N5968	Z-Di	=1N5965: 3,3V	31a		—
1N5969	Z-Di	=1N5965: 3,6V	31a		—

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1N599(A)	Si-Di	GI, 50V, 0,4A	34a	USA,Tix	BA157..159, BY401..405, 1N4001..07,++
1N5990	Z-Di	=1N5995: 3,9V	31a		—
1N5991	Z-Di	=1N5985: 4,3V	31a		—
1N5992	Z-Di	=1N5985: 4,7V	31a		—
1N5993	Z-Di	=1N5985: 5,1V	31a		—
1N5994	Z-Di	=1N5985: 5,6V	31a		—
1N5995	Z-Di	=1N5995: 8,2V	31a		—
1N5998	Z-Di	=1N5985: 6,8V	31a		—
1N5997	Z-Di	=1N5985: 7,5V	31a		—
1N5998	Z-Di	=1N5985: 8,2V	31a		—
1N5999	Z-Di	=1N5995: 9,1V	31a		—
1N60(A)	Ge-Di	AM/FM-Dem, TV-ZF-Dem, 50V, 50mA	31a	USA,EUR,JAP	AA113, AA138, 1N34, 1N54
1N600(A)	Si-Di	=1N599: 100V	34a		BA157..159, BY402..405, 1N4002..07,++
1N6000	Z-Di	=1N5985: 10V	31a		—
1N6001	Z-Di	=1N5985: 11V	31a		—
1N6002	Z-Di	=1N5985: 12V	31a		—
1N6003	Z-Di	=1N5985: 13V	31a		—
1N6004	Z-Di	=1N5985: 15V	31a		—
1N6005	Z-Di	=1N5995: 16V	31a		,
1N6006	Z-Di	=1N5985: 18V	31a		—
1N6007	Z-Di	=1N5985: 20V	31a		—
1N6008	Z-Di	=1N5985: 22V	31a		—
1N6009	Z-Di	=1N5985: 24V	31a		—
1N601(A)	Si-Di	=1N599: 150V	34a		BA157..159, BY403..405, 1N4003..07,++
1N6010	Z-Di	=1N5985: 27V	31a		—
1N6011	Z-Di	=1N5985: 30V	31a		—
1N6012	Z-Di	=1N5985: 33V	31a		—
1N6013	Z-Di	=1N5985: 38V	31a		—
1N6014	Z-Di	=1N5985: 39V	31a		—
1N6015	Z-Di	=1N5985: 43V	31a		—
1N6016	Z-Di	=1N5995: 47V	31a		—
1N6017	Z-Di	=1N5985: 51V	31a		—
1N6018	Z-Di	=1N5985: 56V	31a		—
1N6019	Z-Di	=1N5985: 62V	31a		—
1N602(A)	Si-Di	=1N599: 200V	34a		BA157..159, BY403..405, 1N4003..07,++
1N6020	Z-Di	=1N5985: 88V	31a		—
1N6021	Z-Di	=1N5995: 75V	31a		—
1N6022	Z-Di	=1N5985: 82V	31a		—
1N6023	Z-Di	=1N5985: 91V	31a		—
1N6024	Z-Di	=1N5985: 100V	31a		—
1N6025	Z-Di	=1N5985: 110V	31a		—
1N6026	Z-Di	=1N5985: 120V	31a		—
1N6027	Z-Di	=1N5995: 130V	31a		—
1N6028	Z-Di	=1N5985: 150V	31a		—
1N6029	Z-Di	=1N5985: 160V	31a		,
1N603(A)	Si-Di	=1N599: 300V	34a		BA157..159, BY404..405, 1N4004..07,++
1N6030	Z-Di	=1N5985: 180V	31a		—
1N6031	Z-Di	=1N5985: 200V	31a		—
1N6036(A)	Z-Di	=1N5630: bidirektional/bi-polarity	34a	USA,Tho	1N6138..6173
1N6037(A)	Z-Di	=1N5631: bidirektional/bi-polarity	34a		—
1N6038(A)	Z-Di	=1N5632 bidirektional/bi-polarity	34a		—
1N6039(A)	Z-Di	=1N5633: bidirektional/bi-polarity	34a		—
1N604(A)	Si-Di	=1N599: 400V	34a		BA157..159, BY404..405, 1N4004..07,++
1N6040(A)	Z-Di	=1N5634: bidirektional/bi-polarity	34a		—
1N8041(A)	Z-Di	=1N5635: bidirektional/bi-polarity	34a		—
1N6042(A)	Z-Di	=1N5636: bidirektional/bi-polarity	34a		—
1N6043(A)	Si-Di	=1N5637: bidirektional/bi-polarity	34a		—
1N6044(A)	Z-Di	=1N5638: bidirektional/bi-polarity	34a		—
1N6045(A)	Z-Di	=1N5639: bidirektional/bi-polarity	34a		—
1N6046(A)	Z-Di	=1N5640: bidirektional/bi-polarity	34a		—
1N6047(A)	Z-Di	=1N5641: bidirektional/bi-polarity	34a		—
1N6048(A)	Z-Di	=1N5642: bidirektional/bi-polarity	34a		—
1N6049(A)	Z-Di	=1N5643: bidirektional/bi-polarity	34a		—
1N605(A)	Si-Di	=1N599: 500V	34a		BA156..159, BY405, 1N4005..07,++
1N6050(A)	Z-Di	=1N5644: bidirektional/bi-polarity	34a		—
1N6051(A)	Z-Di	=1N5645: bidirektional/bi-polarity	34a		—

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1N6052(A)	Z-Di	=1N5646: bidirektional/bi-polarity	34a		—
1N6053(A)	Z-Di	=1N5647: bidirektional/bi-polarity	34a		—
1N6054(A)	Z-Di	=1N5646: bidirektional/bi-polarity	34a		—
1N6055(A)	Z-Di	=1N5649: bidirektional/bi-polarity	34a		—
1N6056(A)	Z-Di	=1N5650: bidirektional/bi-polarity	34a		—
1N6057(A)	Z-Di	=1N5651: bidirektional/bi-polarity	34a		—
1N6058(A)	Z-Di	=1N5652: bidirektional/bi-polarity	34a		—
1N6059(A)	Z-Di	=1N5653: bidirektional/bi-polarity	34a		—
1N606(A)	Si-Di	=1N599: 600V	34a		BA158..159, BY405, 1N4005..07,++
1N6060(A)	Z-Di	=1N5654: bidirektional/bi-polarity	34a		—
1N6061(A)	Z-Di	=1N5655: bidirektional/bi-polarity	34a		—
1N6062(A)	Z-Di	=1N5656: bidirektional/bi-polarity	34a		—
1N6063(A)	Z-Di	=1N5657: bidirektional/bi-polarity	34a		—
1N6064(A)	Z-Di	=1N5658: bidirektional/bi-polarity	34a		—
1N6065(A)	Z-Di	=1N5659: bidirektional/bi-polarity	34a		—
1N6066(A)	Z-Di	=1N5660: bidirektional/bi-polarity	34a		—
1N6067(A)	Z-Di	=1N5661: bidirektional/bi-polarity	34a		—
1N6068(A)	Z-Di	=1N5662: bidirektional/bi-polarity	34a		—
1N6069(A)	Z-Di	=1N5663: bidirektional/bi-polarity	34a		—
1N607(A)	Si-Di	GI-L, 50V, 1A	32a	USA,Tix	BYX38/300, BYX39/600
1N6070(A)	Z-Di	=1N5664: bidirektional/bi-polarity	34a		—
1N6071(A)	Z-Di	=1N5665: bidirektional/bi-polarity	34a		—
1N6072(A)	Z-Di	=1N5665: 220V, bidirektional/bi-pol.	34a		—
1N6073	Si-Di	GI, S, 50V, 3A, 30ns	31a	Msc,Smt	BYV28/50, EGP30A, FE3A
1N6074	Si-Di	=1N6073: 100V	31a		BYV28/100, EGP30B, FE3B
1N6075	Si-Di	=1N6073: 150V	31a		BYV28/150, EGP30C, FE3C
1N6076	Si-Di	GI, S, 50V, 6A, 30ns	31a	Msc,Smt	BYV61..63, FE6A
1N6077	Si-Di	=1N6076: 100V	31a		BYV61..63, FE6A
1N6076	Si-Di	=1N6076: 150V	31a		BYV81..63, FE6A
1N6079	Si-Di	GI, S, 50V, 12A, 30ns	31a	Msc,Smt	—
1N607R...614R	Si-Di	=1N607(A)..614(A):	32b		BYX38/600R, BYX39/600R
1N606(A)	Si-Di	=1N607(A): 100V	32a		BYX38/300, BYX39/600
1N6080	Si-Di	=1N6079: 100V	31a		—
1N6081	Si-Di	=1N6079: 160V	31a		—
1N6082	Z-Di	4,3V, 20%, 0,4W	31a	Ksw,Msc,Trw	BZX55/.., BZX79/.., ZPD.., 1N5229..40,++
1N6082A...6091A	Z-Di	=1N6082..6091: 10%	31a		—
1N6082B...6091B	Z-Di	=1N6082..6091: 5%	31a		—
1N6062C...6091C	Z-Di	=1N6062..6091: 2%	31a		—
1N6082D...6091D	Z-Di	=1N6082..6091: 1%	31a		—
1N6083	Z-Di	=1N6062: 4,7V	31a		—
1N8084	Z-Di	=1N6062: 5,1V	31a		—
1N6085	Z-Di	=1N6082: 5,6V	31a		—
1N6086	Z-Di	=1N6062: 6,2V	31a		—
1N6087	Z-Di	=1N6082: 6,8V	31a		—
1N6088	Z-Di	=1N6082: 7,5V	31a		—
1N6089	Z-Di	=1N6062: 8,2V	31a		—
1N609(A)	Si-Di	=1N607(A): 150V	32a		BYX38/3+F625200, BYX39/600
1N6090	Z-Di	=1N6082: 9,1V	31a		—
1N6091	Z-Di	=1N6082: 10V	31a		—
1N6095	Si-Di	Schottky-GI, 30V, 25A(Tc=70°)	32a	USA,Inr,Mot	BYS30..32, BYV121/35, MBR2530
1N6096	Si-Di	=1N6095: 40V	32a		BYS30..32, BYV121/40, MBR2540
1N6097	Si-Di	Schottky-GI, 30V, 50A(Tc=70°)	32a	USA,Inr,Mot	BYS50..51, BYS60/30, MBR6030
1N6098	Si-Di	=1N6098: 40V	32a		BYS50..51, BYS60/40, MBR6045
1N6099	Si-Di	=1N3595	31a	Fch	→1N3595
1N61	Ge-Di	Uni, 140V, 40mA	31a	USA	AA133, 1N39
1N610(A)	Si-Di	=1N607(A): 200V	32a		BYX38/3800, BYX39/600
1N6100	Si-Di	7-Di Array, 85V, 0,35A, <15ns	14-FLP	Fch	—
1N6101	Si-Di	=1N6100:	14-DIP		—
1N6102(A)	Z-Di	TAZ, bidirektional, 6,8V, 500W(1ms)	31a	USA,Gie,Tho	BZW06/..B
1N6103(A)	Z-Di	=1N6102: 7,5V	31a		—
1N6104(A)	Z-Di	=1N6102: 8,2V	31a		—
1N6105(A)	Z-Di	=1N6102: 9,1V	31a		—
1N6106(A)	Z-Di	=1N6102: 10V	31a		—
1N6107(A)	Z-Di	=1N6102: 11V	31a		—
1N6108(A)	Z-Di	=1N6102: 12V	31a		—
1N6109(A)	Z-Di	=1N6102: 13V	31a		—

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1N611(A)	Si-Di	=1N607(A): 300V	32a		BYX38/300, BYX39/600
1N6110(A)	Z-Di	=1N6102: 15V	31a		—
1N6111(A)	Z-Di	=1N6102: 16V	31a		—
1N6112(A)	Z-Di	=1N6102: 18V	31a		—
1N6113(A)	Z-Di	=1N6102: 20V	31a		—
1N6114(A)	Z-Di	=1N6102: 22V	31a		—
1N6115(A)	Z-Di	=1N6102: 24V	31a		—
1N6116(A)	Z-Di	=1N6102: 27V	31a		—
1N6117(A)	Z-Di	=1N6102: 30V	31a		—
1N6118(A)	Z-Di	=1N6102: 33V	31a		—
1N6119(A)	Z-Di	=1N6102: 36V	31a		—
1N612(A)	Si-Di	=1N607(A): 400V	32a		BYX38/600, BYX39/600
1N6120(A)	Z-Di	=1N6102: 39V	31a		—
1N6121(A)	Z-Di	=1N6102: 43V	31a		—
1N6122(A)	Z-Di	=1N6102: 47V	31a		—
1N6123(A)	Z-Di	=1N6102: 51V	31a		—
1N6124(A)	Z-Di	=1N6102: 56V	31a		—
1N6125(A)	Z-Di	=1N6102: 62V	31a		—
1N6126(A)	Z-Di	=1N6102: 68V	31a		—
1N6127(A)	Z-Di	=1N6102: 75V	31a		—
1N6128(A)	Z-Di	=1N6102: 82V	31a		—
1N6129(A)	Z-Di	=1N6102: 91V	31a		—
1N613(A)	Si-Di	=1N607(A): 500V	32a		BYX38/600, BYX39/500
1N6130(A)	Z-Di	=1N6102: 100V	31a		—
1N6131(A)	Z-Di	=1N6102: 110V	31a		—
1N6132(A)	Z-Di	=1N6102: 120V	31a		—
1N6133(A)	Z-Di	=1N6102: 130V	31a		—
1N6134(A)	Z-Di	=1N6102: 150V	31a		—
1N6135(A)	Z-Di	=1N6102: 160V	31a		—
1N6136(A)	Z-Di	=1N6102: 180V	31a		—
1N6137(A)	Z-Di	=1N6102: 200V	31a		—
1N6138(A)	Z-Di	TAZ, bidirektional, 6,8V, 1,5kW	31a	USA, Tho	1N6036..6072
1N6139(A)	Z-Di	=1N6136: 7,5V	31a		—
1N614(A)	Si-Di	=1N607(A): 600V	32a		BYX38/600, BYX39/600
1N6140(A)	Z-Di	=1N6136: 8,2V	31a		—
1N6141(A)	Z-Di	=1N6136: 9,1V	31a		—
1N6142(A)	Z-Di	=1N6136: 10V	31a		—
1N6143(A)	Z-Di	=1N6136: 11V	31a		—
1N6144(A)	Z-Di	=1N6136: 12V	31a		—
1N6145(A)	Z-Di	=1N6136: 13V	31a		—
1N6146(A)	Z-Di	=1N6136: 15V	31a		—
1N6147(A)	Z-Di	=1N6136: 16V	31a		—
1N6148(A)	Z-Di	=1N6136: 18V	31a		—
1N6149(A)	Z-Di	=1N6136: 20V	31a		—
1N615	Ge-Di	Uni, 300V, 75mA	31a	USA	—
1N6150(A)	Z-Di	=1N6136: 22V	31a		—
1N6151(A)	Z-Di	=1N6136: 24V	31a		—
1N6152(A)	Z-Di	=1N6136: 27V	31a		—
1N6153(A)	Z-Di	=1N6136: 30V	31a		—
1N6154(A)	Z-Di	=1N6136: 33V	31a		—
1N6155(A)	Z-Di	=1N6136: 36V	31a		—
1N6156(A)	Z-Di	=1N6136: 39V	31a		—
1N6157(A)	Z-Di	=1N6136: 43V	31a		—
1N6158(A)	Z-Di	=1N6136: 47V	31a		—
1N6159(A)	Z-Di	=1N6136: 51V	31a		—
1N616	Ge-Di	Dem, 30V, 30mA	31a	USA	AA113..114, AA116, AA119, 1N60, ++
1N6160(A)	Z-Di	=1N6136: 56V	31a		—
1N6161(A)	Z-Di	=1N6136: 62V	31a		—
1N6162(A)	Z-Di	=1N6136: 68V	31a		—
1N6163(A)	Z-Di	=1N6136: 75V	31a		—
1N6164(A)	Z-Di	=1N6136: 82V	31a		—
1N6165(A)	Z-Di	=1N6136: 91V	31a		—
1N6166(A)	Z-Di	=1N6136: 100V	31a		—
1N6167(A)	Z-Di	=1N6136: 110V	31a		—
1N6168(A)	Z-Di	=1N6136: 120V	31a		—
1N6169(A)	Z-Di	=1N6136: 130V	31a		—

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1N617	Ge-Di	Uni, 90V, 50mA	31a	USA	AA117..118, AA132..133
1N6170(A)	Z-Di	=1N6138: 150V	31a		—
1N6171(A)	Z-Di	=1N6138: 160V	31a		—
1N6172(A)	Z-Di	=1N6138: 160V	31a		—
1N8173(A)	Z-Di	=1N6138: 200V	31a		—
1N618	Ge-Di	Uni, 90V, 50mA	31a	USA	AA117..118, AA132..133
1N619	Si-Di	Uni, 30V	31a	USA	BA127..128, BA222, BA147/50, 1N4148++
1N61A1	Si-Di	=1N44A1: 30kV		Tos	—
1N62	Ge-Di	Uni, 140V, 40mA	31a	USA	AA133, 1N39
1N622	Si-Di	Uni, 150V	31a	USA	BA147/150, 1N5195..96, 1N5606..07, ++
1N625(A)	Si-Di	S, 30V, 20mA, <500..1000ns	31a	Fch, Tix, ++	BA195, BAW49, BAX15..17, 1N3070, ++
1N626(A)	Si-Di	=1N625: 50V	31a		BA195, BAW49, BAX15..17, 1N3070, ++
1N6262	Si-Di	Gl-L, 200V, 85A(Tc=100°)	32a	Sie	—
1N6263	Si-Di	Schottky-Di, VHF/UHF-Dem, 60V, 15mA	31a	Hew, Itt, Tho	BAR28, HSS100, HSS102
1N6267(A)	Z-Di	=1N5629:	31a	Gsi, Mot, Scn	(1N6038..6072, 1N6138..6173)
1N6268(A)	Z-Di	=1N5630:	31a		—
1N6269(A)	Z-Di	=1N5631:	31a		—
1N627(A)	Si-Di	=1N625: 100V	31a		BA195, BAW49, BAX15..17, 1N3070, ++
1N6270(A)	Z-Di	=1N5632:	31a		—
1N6271(A)	Z-Di	=1N5633:	31a		—
1N6272(A)	Z-Di	=1N5634:	31a		—
1N6273(A)	Z-Di	=1N5635:	31a		—
1N6274(A)	Z-Di	=1N5638:	31a		—
1N6275(A)	Z-Di	=1N5637:	31a		—
1N6276(A)	Z-Di	=1N5638:	31a		—
1N6277(A)	Z-Di	=1N5639:	31a		—
1N6278(A)	Z-Di	=1N5640:	31a		—
1N6279(A)	Z-Di	=1N5641:	31a		—
1N628(A)	Si-Di	=1N625: 150V	31a		BA195, BAW50, BAX15..17, 1N3070, ++
1N6280(A)	Z-Di	=1N5642:	31a		—
1N6281(A)	Z-Di	=1N5643:	31a		—
1N6282(A)	Z-Di	=1N5644:	31a		—
1N6283(A)	Z-Di	=1N5645:	31a		—
1N6284(A)	Z-Di	=1N5646:	31a		—
1N6285(A)	Z-Di	=1N5647:	31a		—
1N6286(A)	Z-Di	=1N5648:	31a		—
1N6287(A)	Z-Di	=1N5649:	31a		—
1N6268(A)	Z-Di	=1N5650:	31a		—
1N6289(A)	Z-Di	=1N5651:	31a		—
1N629(A)	Si-Di	=1N625: 200V	31a		BA195, BA197, BAW50, BAX17, ++
1N6290(A)	Z-Di	=1N5652:	31a		—
1N6291(A)	Z-Di	=1N5653:	31a		—
1N6292(A)	Z-Di	=1N5654:	31a		—
1N6293(A)	Z-Di	=1N5655:	31a		—
1N6294(A)	Z-Di	=1N5656:	31a		—
1N6295(A)	Z-Di	=1N5657:	31a		—
1N6296(A)	Z-Di	=1N5656:	31a		—
1N6297(A)	Z-Di	=1N5659:	31a		—
1N6298(A)	Z-Di	=1N5660:	31a		—
1N6299(A)	Z-Di	=1N5661:	31a		—
1N63(A)	Ge-Di	Uni, 100V, 30..50mA	31a	USA, Tho	AA117..118, AA132..133
1N630(A)	Si-Di	UHF, L/X-Band-Dem	Koax	Miv, Syl	—
1N6300(A)	Z-Di	=1N5662:	31a		—
1N6301(A)	Z-Di	=1N5663:	31a		—
1N6302(A)	Z-Di	=1N5664:	31a		—
1N6303(A)	Z-Di	=1N5665:	31a		—
1N6304	Si-Di	Gl/S-L, 50V, 70A(Tc=100°), <50ns	32a	Uni	BYW07/50, BYW08/50, BYW94/50
1N6304R..6306R	Si-Di	=1N6304..6306:	32b	Uni	BYW07/..R
1N6305	Si-Di	=1N6304: 100V	32a	Uni	BYW07/100, BTW08/100, BYW94/100
1N6306	Si-Di	=1N6304: 150V	32a	Uni	BYW07/150, BTW08/150, BYW94/150
1N6307	Si-Di	40V	31a	Hew	—
1N631	Ge-Di	S, 60V, 60mA, <300ns	31a	USA	AAY28, 1N276
1N632	Ge-Di	S, 60V, <300ns	31a	USA	AAY28, 1N276
1N633	Ge-Di	S, 90V, 60mA, <300ns	31a	USA	AAY28, 1N276
1N634	Ge-Di	Uni, 125V, 100mA	31a	USA	—
1N635	Ge-Di	Uni, 175V, 150mA	31a	USA	—

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1N636	Ge-Di	Uni, 50V, 30mA	31a	USA	AA 117..118, AA 132..134, 1N34, 1N54, ++
1N6373	Z-Di	TAZ, 5V, 1,5kW	31a	Mot	1N5629..49, 1N6267..6387
1N6374	Z-Di	=1N6373: 8V	31a		—
1N6375	Z-Di	=1N6373: 10V	31a		—
1N6376	Z-Di	=1N6373: 12V	31a		—
1N6377	Z-Di	=1N6373: 15V	31a		—
1N6378	Z-Di	=1N6373: 18V	31a		—
1N6379	Z-Di	=1N6373: 22V	31a		—
1N6360	Z-Di	=1N6373: 36V	31a		—
1N6361	Z-Di	=1N6373: 45V	31a		—
1N6362..6389	Z-Di	=1N6373..6381: bidirektional	31a		1N6036..55, 1N6136..58
1N6391	Si-Di	Schottky-Gl, 45V, 25A(Tc=125°)	32a	Uni	BYS31-.., BYS 32, BYV 121-45
1N6362	Si-Di	Schottky-Gl, 45V, 60A(Tc=115°)	32a	Uni	BYS 50, BYS 32-45, MBR6045
1N64(A)	Ge-Di	Uni, 25V, 50mA	31a	USA, Tho	AA 113, AA 119, 1N34, 1N54, 1N60, ++
1N643(A)	Si-Di	S, 200V, 0,04A, <300ns	31a	Fch, Tix, ++	BA 195, BA 197..198, BAW50, BAX 17, ++
1N645(A,B,GP,J)	Si-Di	Gl, 225V, 0,4A	31a	Gie, Tix, ++	BA157..159, BY 206..207, BY 404..405, ++
1N646(GP)	Si-Di	=1N645: 300V	31a		BA157..159, BY 206..207, BY 404..405, ++
1N6461	Z-Di	TAZ, 5V, 2,5W, 500W(1ms)	31a	Uni	BZW 06/.., BZW70/.., BZX70.., BZY93/..
1N6462	Z-Di	=1N6461: 6V	31a		—
1N6463	Z-Di	=1N6461: 12V	31a		—
1N6464	Z-Di	=1N6461: 15V	31a		—
1N6465	Z-Di	=1N6461: 24V	31a		—
1N6466	Z-Di	=1N6461: 30,5V	31a		—
1N6467	Z-Di	=1N6461: 40,3V	31a		—
1N6466	Z-Di	=1N6461: 51,6V	31a		—
1N647(GP)	Si-Di	=1N645: 400V	31a		BA157..159, BY 207, BY 404..405, ++
1N6478	Si-Di	SMD, Gl, 50V, 1A	72a(5mm)	Gie	BYM 11-50, BYM 12-50
1N6479	Si-Di	=1M6478: 100V	72a(5mm)		BYM 11-100, BYM 12-100
1N648(GP)	Si-Di	=1N645: 500V	31a		BA 158..159, BY 207, BY 405, 1N4005, ++
1N6480	Si-Di	=1M6478: 200V	72a(5mm)		BYM 11-200, BYM 12-200
1N6481	Si-Di	=1M6478: 400V	72a(5mm)		BYM 11-400, BYM 12-400
1N6462	Si-Di	=1M6478: 600V	72a(5mm)		BYM 11-600, BYM 12-600
1N6463	Si-Di	=1M6478: 600V	72a(5mm)		BYM 11-600, BYM 12-600
1N6484	Si-Di	=1M6478: 1000V	72a(5mm)		BYM 11-1000, BYM 12-1000
1N649(GP)	Si-Di	=1N645: 600V	31a		BA 158..159, BY 207, BY 405, 1N4005, ++
1N6492	Si-Di	Schottky-Gl, 45V, 1,2A	2c	Uni	(BYS 22-45, BYS 26-45, MBR350, ++)
1N6496	Si-Di	16xDi Array, 80V, <10ns	20Pin	Fch	—
1N65	Ge-Di	HF-Dem, 70V, 50mA	31a	USA, Tho	AA 113, 1N34, 1N54, 1N60
1N650	GaAs-Di	Tunnel-Di	31	Tix	—
1N651	GaAs-Di	Tunnel-Di	31	Tix	—
1N652	GaAs-Di	Tunnel-Di	31	Tix	—
1N653	GaAs-Di	Tunnel-Di	31	Tix	—
1N658(A)	Si-Di	S, 50V, 60mA, <300ns	31a	Fch, Tix, ++	BA 195, BAW 49, BAX 15..17, 1N3070, ++
1N658(A)	Si-Di	S, 50V, 100mA, <300ns	31a	Fch, Tix, ++	BA 195, BAW 49, BAX 15..17, 1N3070, ++
1N66	Ge-Di	Uni, 80V, 50mA	31a	USA, Tho	AA 117..118, AA 132..134, 1N80, ++
1N660(A)	Si-Di	S, 100V, 100mA, <300ns	31a	Fch, Tix, ++	BA 195, BAW 49, BAX 15..17, 1N3070, ++
1N661(A)	Si-Di	S, 200V, 100mA, <300ns	31a	Fch, Tix, ++	BA 195, BA 197..98, BAW50, BAX 17, ++
1N662(A)	Si-Di	S, 80V, 40mA, <500ns	31a	Fch, Tix, ++	BA 195, BAW 49, BAX 15..17, 1N3070, ++
1N6620	Si-Di	S, contr.av., 200V, 1,2A, <30ns	31a	Uni	BYD 73D..G, BYV 27/200
1N6621	Si-Di	S, contr.av., 400V, 1,2A, <30ns	31a	Uni	BYD73G, BYD74G
1N6622	Si-Di	S, contr.av., 600V, 1,2A, <30ns	31a	Uni	—
1N6623	Si-Di	S, contr.av., 600V, 1A, <50ns	31a	Uni	—
1N6624	Si-Di	S, contr.av., 900V, 1A, <50ns	31a	Uni	—
1N6625	Si-Di	S, contr.av., 1000V, 1A, <60ns	31a	Uni	—
1N6626	Si-Di	S, contr.av., 200V, 2A, <30ns	31a	Uni	BYD74D..G, BYV 27/200
1N6627	Si-Di	S, contr.av., 400V, 2A, <30ns	31a	Uni	BYD74G
1N6628	Si-Di	S, contr.av., 600V, 2A, <30ns	31a	Uni	—
1N6629	Si-Di	S, contr.av., 600V, 1,4A, <50ns	31a	Uni	—
1N663(A)	Si-Di	S, 80V, 80mA, <500ns	31a	Fch, Tix, ++	BA 195, BAW 49, BAX 15..17, 1N3070, ++
1N6630	Si-Di	S, contr.av., 900V, 1,4A, <50ns	31a	Uni	—
1N6631	Si-Di	S, contr.av., 1000V, 1,4A, <60ns	31a	Uni	—
1N6636	Si-Di	SS, 150V, 0,3A, <4,5ns	31a	Uni	—
1N6636U..6643U	Si-Di	=1N6638..6643: SMD	72a		—
1N664	Z-Di	8,2V, 5%, 0,4W	34a	USA	BZX55/.., BZX83/.., ZPD.., 1N5230..76, ++
1N6642	Si-Di	SS, 100V, 0,3A, <5ns	31a	Uni	—
1N6643	Si-Di	SS, 75V, 0,3A, <6ns	31a	Uni	BAV 10, BAW55, BAW76

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1N665	Z-Di	=1N664: 12V	34a		—
1N666	Z-Di	=1N664: 15V	34a		—
1N667	Z-Di	=1N664: 18V	34a		—
1N666	Z-Di	=1N664: 22V	34a		—
1N669	Z-Di	=1N664: 27V	34a		—
1N67(A)	Ge-Di	Dem, Uni, 92V, 35mA	31a	USA, Tho	AA113, AA119, 1N34, 1N54, 1N60, ++
1N670	Z-Di	=1N664: 66V	34a		—
1N671	Z-Di	=1N664: 100V	34a		—
1N672	Z-Di	=1N664: 150V	34a		—
1N673	Si-Di	Gl, 350V, 0,4A	≈34a	USA	BA157..159, BY206..207, BY404..405, ++
1N674	Z-Di	=1N664: 4,7V	34a	USA	→1N664..
1N675	Z-Di	=1N664: 6,2V	34a	USA	→1N664..
1N676	Si-Di	Gl, Uni, 100V, 0,2A	31a	Fch, Itt, ++	SA157..159, BA193..194, BA199/250, ++
1N677	Si-Di	Gl, Uni, 100V, 0,4A	31a	Fch, Itt, ++	SA157..159, BA193..194, SA199/250, ++
1N678	Si-Di	Gl, Uni, 200V, 0,2A	31a	Fch, Itt, ++	BA157..159, SA199/250, BAS11, ++
1N679	Si-Di	Gl, Uni, 200V, 0,4A	31a	Fch, Itt, ++	BA157..159, SA199/250, BAS11, ++
1N68(A)	Ge-Di	Uni, 100V, 35mA	31a	USA, Tho	AA117..118, AA132..133
1N681	Si-Di	Gl, Uni, 300V, 0,075A	31a	Fch, Itt, ++	BA199/350, BAS11, SAY21, SAY88..90++
1N662	Si-Di	Gl, Uni, 300V, 0,15A	31a	Fch, Itt, ++	BA199/350, BAS11, BAY21, BAY66..90++
1N683	Si-Di	Gl, Uni, 400V, 0,075A	31a	Fch, Itt, ++	SA157..159, SA199/450, SAY89..90, ++
1N664	Si-Di	Gl, Uni, 400V, 0,15A	31a	Fch, Itt, ++	SA157..159, BA199/450, SAY89..90, ++
1N665	Si-Di	Gl, Uni, 500V, 0,075A	31a	Fch, Itt, ++	SA158..159, SA199/550, SAY89..90, ++
1N666	Si-Di	Gl, Uni, 500V, 0,15A	31a	Fch, Itt, ++	SA158..159, SA199/550, SAY89..90, ++
1N667	Si-Di	Gl, Uni, 600V, 0,075A	31a	Fch, Itt, ++	SA166..159, SA199/550, SAY89..90, ++
1N689	Si-Di	Gl, Uni, 600V, 0,15A	31a	Fch, Itt, ++	BA166..159, SA199/550, SAY89..90, ++
1N89(A)	Ge-Di	Uni, 70V, 40mA	31a	USA, Tho	AA117..118, AA132..134, 1N34, 1N54, ++
1N690	Si-Di	Uni, S, 36V, 0,25A, <800ns	31a	Sai, Tix, ++	SAV17..21, SAW48..50, BAY72, BAX12++
1N891	Si-Di	=1N690: 80V	31a		SAV19..21, SAW48..50, BAY72, BAX12++
1N692	Si-Di	=1N690: 100V	31a		BAV19..21, SAW49..50, SAY72, BAX12++
1N693	Si-Di	=1N690: 130V	31a		BAV16, SAV19..21, SAW50, BAX15, ++
1N695(A)	Ge-Di	S, 20..25V, 0,1..0,15A, 300ns	31a	USA	AAY49, AAZ15, AAZ17
1N696	Si-Di	S, 40V, <5ns		USA	SA318, SAY38, 1N3062..64, 1N4305, ++
1N897	Si-Di	S, 120V, 0,25A, <100ns	≈34a	USA	BA197..98, BAV19..21, BAW50, ++
1N696	Ge-Di	S, 15V, 500ns	31a	USA	AAY49, AAZ15, AAZ18, 1N276
1N699	Ge-Di	S, 105V, 30mA, <300ns	31a	USA	AAY28, 1N191, 1N633
1N70(A)	Ge-Di	Uni, 120V, 30..50mA	31a	USA, Tho	AA117..118, AA132..133
1N701	Z-Di	10V, 5%, 0,4W	≈34a	USA	BZX55/C10, BZX83/C10, ZPD10, 1N5240, ++
1N702	Z-Di	2,6V, 10%, 0,25W	31a	USA, Tho	BZX55/.., BZX79/.., ZPD.., 1N5222..81, ++
1N702A...745A	Z-Di	=1N702..745: 5%	31a		—
1N702B...745B	Z-Di	=1N702..745: 20%	31a		—
1N703	Z-Di	=1N702: 3,5V	31a		—
1N704	Z-Di	=1N702: 4,1V	31a		—
1N705	Z-Di	=1N702: 4,8V	31a		—
1N706	Z-Di	=1N702: 5,8V	31a		—
1N707	Z-Di	=1N702: 7,1V	31a		—
1N706	Z-Di	=1N702: 5,8V	31a		—
1N709	Z-Di	=1N702: 6,2V	31a		—
1N71	Ge-Di	=4x1N56 gep		Alp	—
1N710	Z-Di	=1N702: 6,8V	31a		—
1N711	Z-Di	=1N702: 7,5V	31a		—
1N712	Z-Di	=1N702: 8,2V	31a		—
1N713	Z-Di	=1N702: 9,1V	31a		—
1N714	Z-Di	=1N702: 10V	31a		—
1N715	Z-Di	=1N702: 11V	31a		—
1N716	Z-Di	=1N702: 12V	31a		—
1N717	Z-Di	=1N702: 13V	31a		—
1N718	Z-Di	=1N702: 15V	31a		—
1N719	Z-Di	=1N702: 16V	31a		—
1N72	Ge-Di	UHF-M	31a	Gen	—
1N720	Z-Di	=1N702: 18V	31a		—
1N721	Z-Di	=1N702: 20V	31a		—
1N722	Z-Di	=1N702: 22V	31a		—
1N723	Z-Di	=1N702: 24V	31a		—
1N724	Z-Di	=1N702: 27V	31a		—
1N725	Z-Di	=1N702: 30V	31a		—
1N726	Z-Di	=1N702: 33V	31a		—

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1N727	Z-Di	=1N702:36V	31a		—
1N728	Z-Di	=1N702:39V	31a		—
1N729	Z-Di	=1N702:43V	31a		—
1N73	Ge-Di	4xHF-Dem, gep, 75V, 22mA	4x31a	USA	AA113, 1N34
1N730	Z-Di	=1N702:47V	31a		—
1N731	Z-Di	=1N702:51V	31a		—
1N732	Z-Di	=1N702:56V	31a		—
1N733	Z-Di	=1N702:62V	31a		—
1N734	Z-Di	=1N702:88V	31a		—
1N735	Z-Di	=1N702:75V	31a		—
1N736	Z-Di	=1N702:62V	31a		—
1N737	Z-Di	=1N702:91V	31a		—
1N736	Z-Di	=1N702:100V	31a		—
1N739	Z-Di	=1N702:110V	31a		—
1N74	Ge-Di	4xHF-Dem, gep, 75V, 22mA		USA	—
1N740	Z-Di	=1N702:120V	31a		—
1N741	Z-Di	=1N702:130V	31a		—
1N742	Z-Di	=1N702:150V	31a		—
1N743	Z-Di	=1N702:160V	31a		—
1N744	Z-Di	=1N702:160V	31a		—
1N745	Z-Di	=1N702:200V	31a		—
1N746	Z-Di	3,3V, 10%, 0,4W	31a	USA, Tho	BZX55/.., BZX83/.., ZPD.., 1N5226..42,++
1N746A...759A	Z-Di	=1N746..759:5%	31a		—
1N747	Z-Di	=1N746:3,6V	31a		—
1N746	Z-Di	=1N746:3,9V	31a		—
1N749	Z-Di	=1N746:4,3V	31a		—
1N75	Ge-Di	HF, Uni, 100V, 50mA	31a	USA, Tho	AA117..116, AA132..133
1N750	Z-Di	=1N746:4,7V	31a		—
1N751	Z-Di	=1N746:5,1V	31a		—
1N752	Z-Di	=1N746:5,6V	31a		—
1N753	Z-Di	=1N746:6,2V	31a		—
1N754	Z-Di	=1N746:6,6V	31a		—
1N755	Z-Di	=1N746:7,5V	31a		—
1N756	Z-Di	=1N746:8,2V	31a		—
1N757	Z-Di	=1N746:9,1V	31a		—
1N758	Z-Di	=1N746:10V	31a		—
1N759	Z-Di	=1N746:12V	31a		—
1N76	Si-Di	UHF, X-Band-Dem	Koax	USA	—
1N760	Ge-Di	S, 60V, 100ns	31a	USA	1N631, 1N633
1N761	Z-Di	4,85V, 10%, 0,25W	31a	Mot, Tix,++	BZX55/.., BZX79/.., ZPD.., 1N5230..52,++
1N761A...769A	Z-Di	=1N761:..769:5%	31a		—
1N762	Z-Di	=1N761:5,8V	31a		—
1N763	Z-Di	=1N761:7,1V	31a		—
1N764	Z-Di	=1N761:6,75V	31a		—
1N785	Z-Di	=1N761:10,5V	31a		—
1N766	Z-Di	=1N761:12,7V	31a		—
1N767	Z-Di	=1N761:15,7V	31a		—
1N769	Z-Di	=1N761:19V	31a		—
1N769	Z-Di	=1N761:23,5V	31a		—
1N77	Opto				—
1N770	Ge-Di	S, 20V, 40mA, 350ns	31a	USA	AAY29, 1N191..192
1N771(A,B)	Ge-Di	Uni, 100V, 50..75mA	31a	USA, Gie	AA117..116, AA132..133
1N772(A)	Ge-Di	Uni, 60V, 50..65mA	31a	USA, Gie	AA117..118, AA132..133
1N773(A)	Ge-Di	Uni, 75V, 50..65mA	31a	USA, Gie	AA117..118, AA132..134, 1N34, 1N54,++
1N774(A)	Ge-Di	Uni, 70V, 50..65mA	31e	USA, Gie	AA117..116, AA132..134, 1N34, 1N54,++
1N775	Ge-Di	Uni, 70V, 50mA	31a	USA, Gie	AA117..116, AA132..134, 1N34˜1N54,++
1N776	Ge-Di	Uni, 30V, 45mA	31a	USA, Gie	AA117..116, AA132..134, 1N34, 1N54,++
1N777	Ge-Di	S, 75V, 50mA, 500ns	31a	USA	AAY28, 1N276, 1N633
1N776	Si-Di	S, 116V, 50mA, 300ns	31a	USA	BA195, BAV19..21, BAX15..17,++
1N779	Si-Di	S, 200V, 50mA, 300ns	31a	USA	BA195, BA197..196, BAV20..21, BAX17
1N76	Si-Di	UHF, Ku-Band-M	Koax	USA	—
1N761(A)	Ge-Di	S, 40V, 60mA, <500ns	31a	USA	AAY26, 1N191..192, 1N276
1N769	Ge-Di	S, 60V, 200ns	31a	USA	—
1N769	Si-Di	S, 30V, 0,12A, <500ns	31a	USA	BA195, BAV17..21, BAX15..17, 1N3070++
1N79	Di	Mess-Gl, Meter rectifier	Koax	Alp	—
1N790	Si-Di	S, 30V, 0,12A, <250ns	31a	USA	BA195, BAV17..21, BAX15..17, 1N3070++

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1N791	Si-Di	S, 30V, 0,16A, <500ns	31a	USA	BA195, BAV17..21, BAX15..17, 1N3070++
1N792	Si-Di	S, 30V, 0,2A, <500ns	31a	USA	BA195, BAV17..21, BAX15..17, 1N3070++
1N793	Si-Di	S, 60V, 0,12A, <500ns	31a	USA	BA195, BAV18..21, BAX15..17, 1N3070++
1N794	Si-Di	S, 60V, 0,12A, <250ns	31a	USA	BA195, BAV18..21, BAX15..17, 1N3070++
1N795	Si-Di	S, 60V, 0,16A, <500ns	31a	USA	BA195, BAV18..21, BAX15..17, 1N3070++
1N796	Si-Di	S, 60V, 0,2A, <500ns	31a	USA	BA195, BAV18..21, BAX15..17, 1N3070++
1N797	Si-Di	S, 120V, 0,12A, <500ns	31a	USA	BA195, BAV19..21, BAX15..17, 1N3070++
1N798	Si-Di	S, 120V, 0,12A, <250ns	31a	USA	BA195, BAV19..21, BAX15..17, 1N3070++
1N799	Si-Di	S, 120V, 0,16A, <500ns	31a	USA	BA195, BAV19..21, BAX15..17, 1N3070++
1N800	Si-Di	S, 120V, 0,2A, <500ns	31a	USA	BA195, BAV19..21, BAX15..17, 1N3070++
1N601	Si-Di	S, 150V, 0,12A, <500ns	31a	USA	BA195, BAV20..21, BAX15..17, 1N3070++
1N602	Si-Di	S, 150V, 0,16A, <500ns	31a	USA	BA195, BAV20..21, BAX15..17, 1N3070++
1N803	Si-Di	S, 200V, 0,12A, <500ns	31a	USA	BA195, BA197..198, BAV20..21, ++
1N804	Si-Di	S, 200V, 0,16A, <500ns	31a	USA	BA195, BA197..198, BAV20..21, ++
1N805	Ge-Di	Uni, 40V	31a	USA	AA117..118, AA132..134, 1N34, 1N54, ++
1N806	Si-Di	S, 125V, 60mA, <300ns	31a	USA	BA195, BAV19..21, BAX15..17, 1N3070++
1N607	Si-Di	S, 200V, 60mA, <300ns	31a	USA	BA195, BA197..198, BAV20..21, BAX17
1N806	Si-Di	S, 110V, 100mA, <300ns	31a	USA	BA195, BAV19..21, BAX15..17, 1N3070++
1N809	Si-Di	S, 220V, 100mA, <300ns	31a	USA	BA195, BA197..198, BAV20..21, BAX17
1N81(A)	Ge-Di	Uni, 50V, 30mA	31a	USA,Nec,Tho	AA117..118, AA132..134, 1N60, ++
1N810	Si-Di	S, 50V, <50ns	=34a	USA	BY208/600, BY295/150, BY406..407, ++
1N811	Si-Di	S, 30V, 0,04A, <250ns	31a	USA	BAV17..21, BAX15..17, 1N3070, ++
1N812	Si-Di	S, 40V, 0,06A, <250ns	31a	USA	BAV18..21, SAX15..17, 1N3070, ++
1N813	Si-Di	S, 20V, 0,075A, <250ns	31a	USA	BAV17..21, BAX15..17, 1N3070, ++
1N814	Si-Di	S, 50V, 0,06A, <250ns	31a	USA	SAV18..21, BAX15..17, 1N3070, ++
1N815	Si-Di	S, 25V, 0,12A, <250ns	31a	USA	SAV17..21, BAX15..17, 1N3070, ++
1N816	Si-St	0,58..0,7V	31a	USA,Mot	BA220, BZ102/OV7, BZX55/C0V8, BZX62,++
1N817	Si-Di	S, 200V, <1μs	31a	old	BA147/230, BA190, 1N5195..96, ++
1N818	Si-Di	S, 80V, 0,055A, <500ns	31a	USA	BA195, BAV19..20, BAX15..17, 1N3070++
1N819	Si-Di	80V			—
1N62(A)	Si-Di	UHF-M	31a	Tho	—
1N821(A)	Ref-Di	8,2V, 5%, 0,25W	31a	USA,EUR	BZV10, BZV27, BZX90
1N822(A)	Ref-Di	bidirektional, 6,2V, 5%, 0,25W	31a		—
1N823(A)	Ref-Di	6,2V, 5%, 0,25W	31a		BZV11, BZV28, BZX91
1N824(A)	Ref-Di	bidirektional, 8,2V, 5%, 0,25W	31a		—
1N825(A)	Ref-Di	6,2V, 5%, 0,25W	31a		BZV12, BZV29, BZX92
1N826(A)	Ref-Di	6,55V, 5%, 0,25W	31a		BZV12, BZV29, BZX92
1N627(A)	Ref-Di	6,2V, 5%, 0,25W	31a		BZV13, BZV30, BZX93
1N628(A)	Ref-Di	6,55V, 5%, 0,25W	31a		BZV13, BZV30, BZX93
1N829(A)	Ref-Di	6,2V, 5%, 0,25W	31a		BZV14, BZV51, BZX94
1N83	Ge-Di	Uni, 375V	31a	Idc	—
1N830(A)	Si-Di	UHF-Dem	31a	USA	—
1N831(A,B,C)	Si-Di	UHF, S-Band-M	31a	USA	—
1N832(A,B,C)	Si-Di	UHF, X-Band-M	31a	USA	—
1N833(A)	Si-Di	UHF, X-Band-Dem	31a	USA	—
1N635	Ge-Di	S, 30V, 70mA, <500ns	31a	USA	AAY49, AAZ15, AAZ17
1N636	Ge-Di	UHF, 5V	31a	old	—
1N837(A)	Si-Di	S, 100V, 0,1A, <500ns	31a	USA	BA195, BAV19..21, BAX15..17, 1N3070++
1N838	Si-Di	S, 150V, 0,1A, <500ns	31a	USA	BA195, BAV20..21, BAX15..17, 1N3070++
1N839	Si-Di	S, 200V, 0,1A, <500ns	31a	USA	BA195, BA197..198, BAV20..21, BAX17
1N84	Ge-Di	HF, Uni, 25V	31a	USA	AA113, AA119, 1N34, 1N54, 1N60
1N840	Si-Di	S, 50V, 0,1A, <300ns	31a	USA	BA195, BAV18..21, BAX15..17, 1N3070++
1N841	Si-Di	S, 150V, 0,1A, <300ns	31a	USA	BA195, BAV20..21, BAX15..17, 1N6070++
1N842	Si-Di	S, 200V, 0,1A, <300ns	31a	USA	BA195, BA197..198, BAV20..21, BAX17
1N843	Si-Di	S, 250V, 0,1A, <300ns	31a	USA	BA198, BAV21, BAW173
1N844	Si-Di	S, 100V, 0,2A, <500ns	31a	USA	BA195, BAV19..21, BAX15..17, 1N3070++
1N845	Si-Di	S, 200V, 0,2A, <500ns	31a	USA	BA195, BA197..198, BAV19..21, BAX17
1N848	Si-Di	GI, Uni, 50V, 0,2A	31a	USA	BA157..159, BAY86..90, BY204/4, ++
1N847	Si-Di	=1N846: 100V	31a		BA157..159, BAY87..90, BY204/4, ++
1N848	Si-Di	=1N846: 200V	31a		BA157..159, BAY86..90, BY204/4, ++
1N849	Si-Di	=1N846: 300V	31a		BA157..159, BAY86..90, BY204/4, ++
1N85	Opto				—
1N850	Si-Di	=1N848: 400V	31a		BA157..159, BAY89..90, BY204/4, ++
1N851	Si-Di	=1N846: 500V	31a		BA158..159, BAY89..90, BY204/8, ++
1N852	Si-Di	=1N846: 800V	31a		BA158..159, BAY89..90, BY204/8, ++
1N853	Si-Di	=1N846: 700V	31a		BA158..159, BAY90..91, BY204/8, ++

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1N854	Si-Di	=1N846: 800V	31a		BA158..159, BAY90..91, BY204/8, ++
1N855	Si-Di	=1N846: 900V	31a		BA159, BAY90..91, BY204/10, ++
1N856	Si-Di	=1N846: 1000V	31a		BA159, BAY90..91, BY204/10, ++
1N857	Si-Di	Gl, Uni, 50V, 0,15A	31a	USA	BA157..159, BAY88..90, BY204/4, ++
1N858	Si-Di	=1N857: 100V	31a		BA157..159, BAY87..90, BY204/4, ++
1N859	Si-Di	=1N857: 200V	31a		BA157..159, BAY88..90, BY204/4, ++
1N86	Ge-Di	Uni, 70V, 50mA	31a	USA	AA117..118, AA132..134
1N860	Si-Di	=1N857: 300V	31a		BA157..159, BAY86..90, BY204/4, ++
1N861	Si-Di	=1N857: 400V	31a		BA157..159, BAY89..90, BY204/4, ++
1N862	Si-Di	=1N857: 500V	31a		BA158..159, BAY89..90, BY204/8, ++
1N863	Si-Di	=1N857: 600V	31a		BA158..159, BAY89..90, BY204/8, ++
1N864	Si-Di	=1N857: 700V	31a		BA158+F6693..159, BAY90..91, BY204/8, ++
1N865	Si-Di	=1N857: 800V	31a		BA158..159, BAY90..91, BY204/8, ++
1N866	Si-Di	=1N857: 900V	31a		BA159, BAY90..91, BY204/10, ++
1N867	Si-Di	=1N857: 1000V	31a		BA159, BAY90..91, BY204/10, ++
1N866	Si-Di	Gl, Uni, 50V, 0,1A	31a	USA	BA157..159, BAY86..90, BY204/4, ++
1N869	Si-Di	=1N886: 100V	31a		BA157..159, BAY87..90, BY204/4, ++
1N87(A..T)	Ge-Di	AM/FM-Dem, 25..30V, 30..50mA	31a	USA, EUR, Tos	AA112..114, AA119, 1N34, 1N54, 1N60, ++
1N870	Si-Di	=1N868: 200V	31a		BA157..159, BAY86..90, BY204/4, ++
1N871	Si-Di	=1N868: 300V	31a		BA157..159, BAY88..90, BY204/4, ++
1N872	Si-Di	=1N886: 400V	31a		BA157..159, BAY89..90, BY204/4, ++
1N873	Si-Di	=1N886: 500V	31a		BA158..159, BAY89..90, BY204/8, ++
1N874	Si-Di	=1N868: 600V	31a		BA158..159, BAY89..90, BY204/8, ++
1N875	Si-Di	=1N868: 700V	31a		BA158..159, BAY90..91, BY204/8, ++
1N876	Si-Di	=1N868: 800V	31a		BA158..159, BAY90..91, BY204/8, ++
1N877	Si-Di	=1N868: 800V	31a		BA159, BAY90..91, BY204/10, ++
1N878	Si-Di	=1N868: 1000V	31a		BA159, BAY90..91, BY204/10, ++
1N879	Si-Di	Gl, Uni, 50V, 0,05A	31a	USA	BA157..159, BAY86..90, BY204/4, ++
1N88	Ge-Di	HF, Uni, 100V	31a	USA	AA117..118, AA132..133
1N880	Si-Di	=1N879: 100V	31a		BA157..159, BAY87..90, BY204/4, ++
1N881	Si-Di	=1N879: 200V	31a		BA157..159, BAY88..90, BY204/4, ++
1N862	Si-Di	=1N879: 300V	31a		BA157..159, BAY88..90, BY204/4, ++
1N863	Si-Di	=1N879: 400V	31a		BA157..159, BAY89..90, BY204/4, ++
1N884	Si-Di	=1N879: 500V	31a		BA158..159, BAY89..90, BY204/8, ++
1N885	Si-Di	=1N879: 600V	31a		BA158..159, BAY89..90, BY204/8, ++
1N886	Si-Di	=1N879: 700V	31a		BA158..159, BAY90..91, BY204/8, ++
1N887	Si-Di	=1N879: 800V	31a		BA158..159, BAY90..91, BY204/8, ++
1N888	Si-Di	=1N879: 900V	31a		BA159, BAY90..91, BY204/10, ++
1N669	Si-Di	=1N879: 1000V	31a		BA159, BAY90..91, BY204/10, ++
1N69	Ge-Di	Uni, 80V, 30mA	31a	USA	AA117..118, AA132..133
1N890	Si-Di	Uni, 90V, 0,1A	31a	USA	BA147/100, BA168..190, 1N5606..09, ++
1N891	Si-Di	S, 90V, 0,2A, 300ns	31a	USA	BA197..198, BAV18..21, BAX15..17, ++
1N892	Si-Di	S, 120V, 0,2A, 300ns	31a	USA	BA197..198, BAV20..21, BAX15..17, ++
1N893	Si-Di	S, 240V, 0,2A, 300ns	31a	USA	BA173, BA198, BAV21
1N894	Ge-Di	UHF, 5V		old	—
1N695	Ge-Di	UHF, 5V		old	—
1N898	Ge-Di	UHF, 5V		old	—
1N697	Si-Di	Min, S, Uni, 50V, 0,03A, <1ns	31a	Sem	(BAX85, BAX89, BAX90, BAX94, ++)
1N898	Si-Di	Min, S, Uni, 50V, 0,06A, <300ns	31a	Sem	(BAX85, BAX89, BAX90, BAX94, ++)
1N899	Si-Di	Min, S, Uni, 100V, 0,03A, <300ns	31a	Sem	(BA197..198, BAV19..21, BAX15..17, ++)
1N90	Ge-Di	Uni, 80V, 30mA	31a	USA, Tho	AA117..118, AA132..134, 1N34, 1N54, ++
1N900	Si-Di	Min, S, Uni, 100V, 0,05A, <300ns	31a	Sem	(BA197..198, BAV19..21, BAX15..17, ++)
1N901	Si-Di	Min, S, Uni, 100V, 0,06A, <300ns	31a	Sem	(BA197..198, BAV19..21, BAX15..17, ++)
1N902	Si-Di	Mm, S, Uni, 200V, 0,03A, <300ns	31a	Sem	(BA197..198, BAV20..21, BAX17, ++)
1N903(A)	Si-Di	S, 20..40V, 0,05..0,075A, <4ns	31a	USA, Sgs	BA218, BAX13, BAX91, 1N4146, ++
1N904(A)	Si-Di	S, 30V, 0,05..0,075A, <4ns	31a	USA, Sgs	BA218, BAX13, BAX91, 1N4148, ++
1N905(A)	Si-Di	S, 20V, 0,05..0,075A, <4ns	31a	USA, Sgs	BA218, BAX13, BAX91, 1N4148, ++
1N906(A)	Si-Di	S, 20V, 0,05..0,075A, <4ns	31a	USA, Sgs	BA218, BAX13, BAX91, 1N4148, ++
1N907(A)	Si-Di	S, 30V, 0,05..0,075A, <4ns	31a	USA, Sgs	BA218, BAX13, BAX91, 1N4148, ++
1N906(A)	Si-Di	S, 40V, 0,05..0,075A, <4ns	31a	USA, Sgs	BA218, BAX13, BAX91, 1N4146, ++
1N909	Ge-Di	Uni, 60V, 100mA	31a	USA	AA136, 1N270, 1N634..635
1N91	Ge-Di	Gl, 100V, 1A	34a	Gen, Mot, Sld	—
1N910	Ge-Di	=1N909: 30V	31a		AA135..136, 1N270, 1N634..635
1N911	Ge-Di	=1N909: 30V	31a		AA135..136, 1N270, 1N634..635
1N912(A)	Ref-Di	0,62V, 0,5W	31a	USA	—
1N913(A)	Ref-Di	0,62V, 0,6W	31a	USA	—

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1N914(A,B)	Si-Di	SS, 100V, 0,2A, <4ns	31a	USA,EUR,JAP	BAW62, BAX95, 1N4148..49, 1N4151, ++
1N915	Si-Di	S, 65V, 0,075A, <10ns	31a	Hit,Tix	BAW62, BAX95, 1N4148..49, 1N4151, ++
1N916(A,B)	Si-Di	SS, 100V, 0,2A, <4ns	31a	USA,EUR,JAP	BAW62, BAX95, 1N4146..49, 1N4151, ++
1N917	Si-Di	SS, 40V, 0,05A, <3ns	31a	Hit,Tix	BAW62, BAX95, 1N4148..49, 1N4151, ++
1N918	Si-Di	UHF, Ku-Band-M	31a	Syl	—
1N919	Si-Di	S, 150V, 0,1A, <300ns	31a	USA	BA195, BAV20..21, BAX15..17, 1N3070++
1N92	Ge-Di	=1N91: 200V	34a		—
1N920	Si-Di	S, 36V, 0,25A, <300ns	31a	USA	BA197..189, BAV17..21, BAX15..17, ++
1N921	Si-Di	S, 70V, 0,25A, <300ns	31a	USA	BA197..189, BAV19..21, BAX15..17, ++
1N922	Si-Di	S, 100V, 0,25A, <300ns	31a	USA	BA197..189, BAV19..21, BAX15..17, ++
1N923	Si-Di	S, 130V, 0,25A, <300ns	31a	USA	BA197..189, BAV19..21, BAX15..17, ++
1N924	Si-Di	Uni, S, 60V, 2µs	31a	USA	BA127, BA188..190, BAY19..21, ++
1N925	Si-Di	S, 40V, 0,12A, <150ns	31a	USA	BA195, BAX16..17, BAY41..43, 1N3070++
1N926	Si-Di	S, 40V, 0,12A, <150ns	31a	USA	BA195, BAX16..17, BAY41..43, 1N3070++
1N927	Si-Di	S, 65V, 0,12A, <150ns	31a	USA	BA195, BAX16..17, BAY42..43, 1N3070++
1N928	Si-Di	=1N927: 120V	31a		BA195, BAX16..17, BAV19..21, 1N3070++
1N929	Si-Di	Uni, 23V, 0,25A	31a	USA	BA192..194, BAW51..52, BAY17..21, ++
1N93(A)	Ge-Di	=1N91: 300V	34a		—
1N930	Si-Di	Uni, 58V, 0,25A	31a	USA	BA193..194, BAW51..52, BAY19..21, ++
1N931	Si-Di	Uni, 115V, 0,25A	31a	USA	BA194, BAW52, BAY20..21, BAY45, ++
1N932	Si-Di	Uni, 230V, 0,25A	31a	USA	BA199/250, BAY21, BAY46, BAY68, ++
1N933	Ge-Di	S, 100V, 30mA, <400ns	31a	USA	AAY28, AAZ15, 1N633
1N934	Si-Di	S, 60V, 30mA, 1µs	31a	USA	BA127, BA147/100, BA188..190, ++
1N935(A,B	Ref-Di	9V, 5%, 0,5W	31a	USA,EUR	1N4765
1N936(A,B)	Ref-Di	9V, 5%, 0,5W	31a		1N4788, 1N4771
1N937(A,B)	Ref-Di	9V, 5%, 0,5W	31a		1N4767, 1N4772
1N938(A,B)	Ref-Di	9V, 5%, 0,5W	31a		1N4788, 1N4773
1N939(A,B)	Ref-Di	9V, 5%, 0,5W	31a		1N4769, 1N4774
1N94	Ge-Di	Gl, 380V, 0,5A			—
1N940(A,B)	Ref-Di	9V, 5%, 0,5W	31a		—
1N941(A,B)	Ref-Di	11,7V, 5%, 0,5W	31a	USA,JAP	1N3580
1N942(A,B)	Ref-Di	11,7V, 5%, 0,5W	31a		1N3581
1N943(A,B)	Ref-Di	11,7V, 5%, 0,5W	31a		1N3582
1N944(A,B)	Ref-Di	11,7V, 5%, 0,5W	31a		1N3583
1N945(A,B)	Ref-Di	11,7V, 6%, 0,5W	31a		1N3584
1N946(A,B)	Ref-Di	11,7V, 5%, 0,5W	31a		—
1N947	Si-Di	Gl, 600V, 0,4A	≈34a	USA	BA158..159, BY204/8, BY207, BY405, ++
1N948	Si-Di	S, 36V, 0,08A, <1µs	31a	USA	BA127, BA147/50, BA187..190, ++
1N949	Ge-Di	Uni, 50V, 0,5A(ss)	31a	USA	AA117..118, AA132..134, 1N34, 1N54, ++
1N95	Ge-Di	Uni, 60V, 30mA	31a	USA	AA117..118, AA132..134, 1N34, 1N54, ++
1N950(A)	Si-Di	VHF-Tuning, 130V, 6..88pF	31a	USA	—
1N951(A)	Si-Di	VHF-Tuning, 90V, 12..120pF	31a	USA	—
1N952(A)	Si-Di	VHF-Tuning, 60V, 20..170pF	31a	USA	—
1N953(A)	Si-Di	VHF-Tuning, 25V, 46..240pF	31a	USA	—
1N954	Si-Di	VHF-Tuning, 25V, 14..88pF	31a	USA	—
1N955	Si-Di	VHF-Tuning, 25V, 22..120pF	31a	USA	—
1N958	Si-Di	VHF-Tuning, 25V, 32..170pF	31a	USA	—
1N957	Z-Di	6,8V, 20%, 0,4W	31a	USA,EUR,JAP	BZX55/.., BZX83/.., ZPD.., 1N5235..81, ++
1N957A...992A	Z-Di	=1N957..992: 10%	31a		—
1N957B...992B	Z-Di	=1N957..992: 5%	31a		—
1N956	Z-Di	=1N957: 7,5V	31a		—
1N959	Z-Di	=1N957: 8,2V	31a		—
1N96(A)	Ge-Di	Uni, 75V, 30..70mA	31a	USA,Nec,Tho	AA117..118, AA132..134, 1N34, 1N54, ++
1N960	Z-Di	=1N957: 9,1V	31a		—
1N951	Z-Di	=1N957: 10V	31a		—
1N962	Z-Di	=1N957: 11V	31a		—
1N963	Z-Di	=1N957: 12V	31a		—
1N954	Z-Di	=1N957: 13V	31a		—
1N955	Z-Di	=1N957: 15V	31a		—
1N966	Z-Di	=1N957: 16V	31a		—
1N967	Z-Di	=1N957: 18V	31a		—
1N968	Z-Di	=1N957: 20V	31a		—
1N969	Z-Di	=1N957: 22V	31a		—
1N97(A)	Ge-Di	Uni, 60..92V, 30mA	31a	USA	AA117..118, AA132..133
1N970	Z-Di	=1N957: 24V	31a		—
1N971	Z-Di	=1N957:C6818 27V	31a		—

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1N972	Z-Di	=1N957: 30V	31a		—
1N973	Z-Di	=1N957: 33V	31a		—
1N974	Z-Di	=1N957: 36V	31a		—
1N975	Z-Di	=1N957: 39V	31a		—
1N976	Z-Di	=1N957: 43V	31a		—
1N977	Z-Di	=1N957: 47V	31a		—
1N976	Z-Di	=1N957: 51V	31a		—
1N979	Z-Di	=1N957: 56V	31a		—
1N98(A)	Ge-Di	HF-Dem, 80V, 30..70mA	31a	USA, Tho	1N34, 1N54
1N980	Z-Di	=1N957: 62V	31a		—
1N981	Z-Di	=1N957: 68V	31a		—
1N982	Z-Di	=1N957: 75V	31a		—
1N983	Z-Di	=1N957: 62V	31a		—
1N984	Z-Di	=1N957: 91V	31a		—
1N985	Z-Di	=1N957: 100V	31a		—
1N986	Z-Di	=1N957: 110V	31a		—
1N987	Z-Di	=1N957: 120V	31a		—
1N988	Z-Di	=1N957: 130V	31a		—
1N989	Z-Di	=1N957: 150V	31a		—
1N99(A)	Ge-Di	Uni, 80..92V, 30mA	31a	USA, Tho	AA117..118, AA132..133
1N990	Z-Di	=1N957: 180V	31a		—
1N991	Z-Di	=1N957: 180V	31a		—
1N992	Z-Di	=1N957: 200V	31a		—
1N993	Si-Di	SS, 20V, 0,02A, <4ns	31a	USA	BA218, BAX13, BAX91, 1N4148..49, ++
1N994	Ge-Di	SS, 6,5V, 0,02A, <2ns	31a	USA	—
1N995	Ge-Di	SS, 10V, 0,03A, <6ns	31a	USA	—
1N996	Ge-Di	S, 20V, 0,05A, <300ns	31a	USA	AAY27..28, 1N631, 1N633, 1N3592
1N997	Si-Di	S, 35V, 0,05A, 150ns	31a	USA	BAX85, BAX99..90, BAX94, 1N4148, ++
1N996	Si-Di	Gl, Uni, 150V	31a	USA	BA157..159, BA194, BAS11, BAW52, ++
1N999	Si-Di	SS, 100V, <4ns	31a	USA	BA219, BAX98
1O...1R		**1O...1R**			
1O	Si-N	=2SD2359(Typ-Code/Stempel/marking)	39		→2SD2359
1OP	N-FET	=2SK198-P (Typ-Code/Stempel/marking)	35		→2SK198
1OP	N-FET	=2SK662-P(Typ-Code/Stempel/marking)	35(2mm)		→2SK662
1OQ	N-FET	=2SK198-Q (Typ-Code/Stempel/marking)	35		→2SK198
1OQ	N-FET	=2SK662-Q(Typ-Code/Stempel/marking)	35(2mm)		→2SK662
1OR	N-FET	=2SK198-R (Typ-Code/Stempel/marking)	35		→2SK198
1OR	N-FET	=2SK662-R(Typ-Code/Stempel/marking)	35(2mm)		→2SK662
1P	Si-N	=FMMT2222A (Typ-Code/Stempel/marking)	35		→FMMT2222A
1P	Si-N	=KST 2222A (Typ-Code/Stempel/marking)	35		→KST 2222A
1P	Si-N	=MMBT 2222A (Typ-Code/Stempel/marking)	35		→MMBT 2222A
1P	Si-N	=YTS 2222A (Typ-Code/Stempel/marking)	35		→YTS 2222A
1P137	Si-P+R	=RT 1P137L (Typ-Code/Stempel/marking)	7(9mm)		→RT 1P137L
1P843	Si-Di	Gl, S, 50V, 1A	31a	Itt	BY201/2, BYX55/350, RGP10A, ++
1P644	Si-Di	=1P643: 100V	31a		BY201/2, BYX55/350, RGP10B, ++
1P845	Si-Di	=1P643: 225V	31a		BY201/3, BYX55/350, RGP10G, ++
1P646	Si-Di	=1P643: 300V	31a		BY201/3, BYX55/350, RGP10G, ++
1P647	Si-Di	=1P643: 400V	31a		BY201/4, BYX55/600, RGP10G, ++
1P649	Si-Di	=1P643: 600V	31a		BY201/6, BYX55/600, RGP10J, ++
1P684	Si-Di	=BY201/12	31a		→BY201/12
1PS181	Si-Di	=1PS193: Dual	35n	Phi	—
1PS164	Si-Di	=1PS193: Dual	35f	Phi	—
1PS193	Si-Di	SMD, SS, 80V, 0,215A, <4ns	35p	Phi	—
1PS226	Si-Di	=1PS193: Dual	35l	Phi	—
1Q	Si-N	=KST 5068 (Typ-Code/Stempel/marking)	35		→KST5088
1Q	Si-N	=MMBT 5088 (Typ-Code/Stempel/marking)	35		→MMBT 5088
1R	Si-N	=2SC4929 (Typ-Code/Stempel/marking)	39		→2SC4929
1R	Si-N	=KST 5089 (Typ-Code/Stempel/marking)	35		→KST 5089
1R	Si-N	=MMBT 5089 (Typ-Code/Stempel/marking)	35		→MMBT 5069
1RM150	Si-Di	=1RM40: 15kV			—
1RM250	Si-Di	=1RM40: 25kV			—
1RM40	Si-Di	kV-Gl, 4kV, 0,5A		Tho	—
1RM80	Si-Di	=1RM40: 8kV			—
1RQ	Si-P	=2SB1565-Q (Typ-Code/Stempel/marking)	≈35		→2SB1585
1RQ	Si-P	=2SB970-Q(Typ-Code/Stempel/marking)	35		→2SB970

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1RR	Si-P	=2SB1585-R (Typ-Code/Stempel/marking)	≈35		→2SB1585
1RR	Si-P	=2SB970-R (Typ-Code/Stempel/marking)	35		→2SB970
1RS	Si-P	=2SB1585-S (Typ-Code/Stempel/marking)	≈35		→2SB1585
1RS	Si-P	=2SB970-S (Typ-Code/Stempel/marking)	35		→2SB970
1 S		**1 S**			
1S	Si-N	=2SD2413 (Typ-Code/Stempel/marking)	39		→2SD2413
1S	Si-N	=MMBT2369A (Typ-Code/Stempel/marking)	35		→MMBT2369A
1S020	Si-Di	Gl, 100V, 1,5A	34a	Tix	BY251..255, BY226..227, 1N5392..99,++
1S021	Si-Di	=1S020: 200V	34a	Tix	BY251..255, BY226..227, 1N5393..99,++
1S023	Si-Di	=1S020: 400V	34a	Tix	BY252..255, BY226..227, 1N5395..99,++
1S025	Si-Di	=1S020: 600V	34a	Tix	BY253..255, BY226..227, 1N5397..99,++
1S027	Si-Di	=1S020: 600V	34a	Tix	BY254..255, BY227, 1N5398..99,++
1S100	Si-Di	Gl, 150V, 0,75A	34a	Tix, Tos	BY126..127, BY133..135, 1N4003..07,++
1S1000(A)	Si-Di	UHF-M, 890MHz	31a	Njr	—
1S1001	Ge-Di	S, 20V, 0,05A, <200ns	31a	Njr	AAY28, 1N631, 1N633
1S1002	Ge-Di	S, 25V, 0,1A, <300ns	31a	Njr	AAY49, AAZ15, AAZ17
1S1003	Ge-Di	Uni, 125V, 0,075A	31a	Njr	AA133, 1N634..835
1S1004	Ge-Di	Uni, 100V, 0,05A	31a	Njr	AA117..118, AA132..133
1S1005	Ge-Di	Uni, 100V, 0,05A	31a	Njr	AA117..118, AA132..133
1S1006	Ge-Di	Uni, 60V, 0,05A	31a	Njr	AA117..118, AA132..133
1S1007	Ge-Di	Uni, 60V, 0,075A	31a	Njr	AA117..118, AA132..133
1S1008	Ge-Di	Uni, 25V, 0,08A	31a	Njr	AA117..118, AA132..134, 1N60,++
1S1009	Ge-Di	Uni, 25V, 0,05A	31a	Njr	AA117..118, AA132..134, 1N60,++
1S100R..109R	Si-Di	=1S100..109:	34b		→1S100..109
1S101	Si-Di	=1S100: 200V	34a		BY126..127, BY133..134, 1N4003..07,++
1S1010	Ge-Di	Uni, 30V, 0,05A	31a	Njr	AA117..118, AA132..134, 1N60,++
1S1011(L,S)	Si-St	0,2..0,35V, 0,05W	31a	Njr	—
1S1012	Si-Di	≈1S871	31a	Org	→1S871
1S1013	Si-Di	≈1S871A	31a	Org	→1S871A
1S1014	Si-Di	≈1S871B	31a	Org	→1S871B
1S1015	Si-Di	≈1S871C	31a	Org	→1S871C
1S1016	Si-Di	≈1S871D	31a	Org	→1S871D
1S1017	Si-Di	≈1S871E	31a	Org	→1S871E
1S1018	Si-Di	≈1S871F	31a	Org	→1S871F
1S1019	Si-Di	≈1S871G	31a	Org	→1S871G
1S102	Si-Di	=1S100: 300V	34a		BY126..127, BY133..134, 1N4004..07,++
1S1020	Si-Di	≈1S871H	31a	Org	→1S871H
1S1021	Si-Di	≈1S881	36a	Org	→1S881
1S1022	Si-Di	≈1S881A	36a	Org	→1S881A
1S1023	Si-Di	≈1S881B	36a	Org	→1S881B
1S1024	Si-Di	≈1S881C	36a	Org	→1S881C
1S1025	Si-Di	≈1S881D	36a	Org	→1S881D
1S1026	Si-Di	≈1S881E	36a	Org	→1S881E
1S1027	Si-Di	≈1S881	31a	Org	→1S881
1S1028	Si-Di	≈1S881A	31a	Org	→1S881A
1S1029	Si-Di	≈1S881B	31a	Org	→1S881B
1S103	Si-Di	=1S100: 400V	34a		BY126..127, BY133..134, 1N4004..07,++
1S1030	Si-Di	≈1S881C	31a	Org	→1S881C
1S1031	Si-Di	≈1S881D	31a	Org	→1S881D
1S1032	Si-Di	≈1S881E	31a	Org	→1S881E
1S1033	Si-Di	Gl-L, 200V, 200A(Tc=110°)	73b	Org	—
1S1034	Si-Di	=1S1033: 300V	73b		—
1S1035	Si-Di	=1S1033: 400V	73b		—
1S1036	Si-Di	=1S1033: 600V	73b		—
1S1037	Si-Di	=1S1033: 800V	73b		—
1S1038	Si-Di	=1S1033: 1000V	73b		—
1S1039	Si-Di	Gl, 400V, 1,5A			(BY205/400, BY252..255, BYX49/600,++)
1S104	Si-Di	=1S100: 500V	34a		BY126..127, BY133..134, 1N4005..07,++
1S1040	Si-Di	=1S1039: 600V			(BY205/600, BY253..255, BYX49/600,++)
1S1041	Si-Di	=1S1039: 600V			(BY205/600, BY254..255, BYX49/900,++)
1S1042	Si-Di	=1S1039: 1000V			(BY205/1000, BY255, BYX49/1000,++)
1S1043	Si-Di	Gl, 400V, 0,75A	34	Org	BY126..127, BY133..134, 1N4004..07,++
1S1044	Si-Di	=1S1043: 600V	34		BY126..127, BY133..134, 1N4005..07,++
1S1045	Si-Di	=1S1043: 600V	34		BY127, BY133, BY227, 1N4006..07,++
1S1046	Si-Di	=1S1043: 1000V	34		BY127, BY133, BY227, 1N4007,++

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1S1047	Si-Di	=1S1043: 1200V	34		BY127, BY133, BY227, GP10Q,++
1S1048	Si-Di	=1S1043: 1400V	34		BY400, BY448, DM513, GP10V,++
1S1049	Si-Di	=1S1043: 1600V	34		BY400, DM513, EM516, GP10Y
1S105	Si-Di	=1S100:C6948 600V	34a		BY126..127, BY133..134, 1N4005..07,++
1S1050	Si-Di	=1S1043: 1600V	34		DM516
1S1051	Si-Di	=1S1043: 2000V	34		—
1S1052	Si-Di	Gl-L, 300V, 3A	≈32a	Org	BYX38/300, BYX39/600
1S1052R..1059R	Si-Di	=1S1052..1059:	≈32b		BYX38/..R, BYX39/..R
1S1053	Si-Di	=1S1052: 400V	≈32a		BYX38/600, BYX39/600
1S1054	Si-Di	=1S1052: 600V	≈32a		BYX38/600, BYX39/600
1S1055	Si-Di	=1S1052: 600V	≈32a		BYX38/900, BYX39/900
1S1056	Si-Di	=1S1052: 1000V	≈32a		BYX38/1200, BYX39/1000
1S1057	Si-Di	=1S1052: 1200V	≈32a		BYX38/1200, BYX39/1200
1S1058	Si-Di	=1S1052: 1400V	≈32a		BYX39/1400
1S1059	Si-Di	=1S1052: 1600V	≈32a		—
1S106	Si-Di	=1S100: 700V	34a		BY127, BY133, BY227, 1N4006..07,++
1S1061	Si-Di	=1S1043: 100V, 1A	31a	Org	→1S1043
1S1062	Si-Di	=1S1043: 200V, 1A	31a		→1S1043
1S1063	Si-Di	=1S1043: 1A	31a		→1S1043
1S1064	Si-Di	=1S1044: 1A	31a		→1S1044
1S1065	Si-Di	=1S1045: 1A	31a		→1S1045
1S1066	Si-Di	=1S1048: 1A	31a		→1S1048
1S1067	Si-Di	=1S1047: 1A	31a		→1S1047
1S1066	Si-Di	=1S1048: 1A	31a		→1S1048
1S1069	Si-Di	=1S1049: 1A	31a		→1S1049
1S107	Si-Di	=1S100: 800V	34a		BY127, BY133, BY227, 1N4006..07,++
1S1070	Si-Di	=1S1050: 1A	31a		→1S1050
1S1071	Si-Di	Gl, 100V, 1,5A	31a	Org	BY226..228, BY251..255, 1N5392..99,++
1S1072	Si-Di	=1S1071: 200V	31a		BY226..228, BY251..255, 1N5393..99,++
1S1073	Si-Di	=1S1071: 400V	31a		BY226..228, BY252..255, 1N5395..99,++
1S1074	Si-Di	=1S1071: 600V	31a		BY226..228, BY253..255, 1N5397..99,++
1S1075	Si-Di	=1S1071: 600V	31a		BY227..226, BY254..255, 1N5398..99,++
1S1076	Si-Di	=1S1071: 1000V	31a		BY227..226, BY255, BYW17/1000, 1N5399,++
1S1077	Si-Di	=1S1071: 1200V	31a		BY227..226, BY255, BYW17/1200,++
1S1078	Si-Di	=1S1071: 1400V	31a		BY228, BY400, BY448
1S1079	Si-Di	=1S1071: 1600V	31a		BY400
1S106	Si-Di	=1S100: 900V	84a		BY127, BY133, BY227, 1N4007,++
1S1080	Si-Di	=1S1071: 1600V	31a		—
1S1061	Si-Di	Gl, 200V, 3A	≈32	Org	BYX38/300, BYX39/600
1S1083	Si-Di	Gl-L, 200V, 55A		Org	—
1S1084	Si-Di	=1S1083: 300V			—
1S1085	Si-Di	=1S1083: 400V			—
1S1066	Si-Di	=1S1083: 500V			—
1S1067	Si-Di	=1S1083: 600V			—
1S1066	Si-Di	=1S1083: 700V			—
1S1089	Si-Di	=1S1083: 800V			—
1S109	Si-Di	=1S100: 1000V	34a		BY127, BY133, BY227, 1N4007,++
1S1090	Si-Di	=1S1083: 1000V			—
1S1091	Si-Di	=1S1063: 1200V			—
1S1092	Si-Di	=1S1068: 1400V			—
1S1093	Si-Di	=1S1083: 1600V			—
1S1094	Z-Di	6,2..8V, 0,2W	31a	Org	BZX55/..., BZX79/..., ZPD..., 1N5234..60,++
1S1095	Z-Di	=1S1094: 7,5..10V	31a		—
1S1096	Z-Di	=1S1094: 9..12V	31a		—
1S1097	Z-Di	=1S1094: 11..14,5V	31a		—
1S1098	Z-Di	=1S1094: 13,5..18V	31a		—
1S1099	Z-Di	=1S1094: 17..21V	31a		—
1S11	Ge-Di	Dem, 80V, 50mA	31a	Mat	AA113, 1N34, 1N60
1S110	Si-Di	Dual, Gl, 500V, 0,4A		Tos	(2xBY126..127, 2xBY133..134,++)
1S1100	Z-Di	=1S1094: 20..27V	31a		—
1S1101	Z-Di	=1S1094: 25..32V	31a		—
1S1102	Z-Di	=1S1094: 30..42V	31a		—
1S1103	Si-Di	kV-Gl, 8kV, 0,15A		Org	—
1S1104	Si-Di	=1S1103: 10kV			—
1S1105	Si-Di	=1S1103: 18kV			—
1S1106	Si-Di	=1S1103: 20kV			—

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1S1107	Si-Di	kV-Gl, 8kV, 0,15A		Org	—
1S1108	Si-Di	=1S1107: 10kV			—
1S1109	Si-Di	=1S1107: 16kV			—
1S1110	Si-Di	=1S1107: 20kV			—
1S1111	Si-Di	kV-Gl, 8kV, 0,15A		Org	—
1S1112	Si-Di	=1S1111: 10kV			—
1S1113	Si-Di	=1S1111: 16kV			—
1S1114	Si-Di	=1S1111: 20kV			—
1S1115	Si-Di	kV-Gl, 8kV, 0,5A		Org	—
1S1116	Si-Di	=1S1115: 10kV			—
1S1117	Si-Di	kV-Gl, 8kV, 0,5A		Org	—
1S1118	Si-Di	=1S1117: 10kV			—
1S1119	Si-Di	=1S1117: 16kV			—
1S111[Japan]	Si-Di	Gl, 100V, 0,75A	34a	Nec	BY126..127, BY133..135, 1N4002..07, ++
1S111[Texas]	Si-Di	Gl, 225V, 0,4A	31a	Tix	BA157..159, BY204/4, 1N4004..07, ++
1S1120	Si-Di	=1S1117: 20kV			—
1S1121	Si-Br	Gl, 100V, 0,3A		Org	B100C300, etc
1S1122	Si-Br	=1S1121: 200V			B200C300, etc
1S1123	Si-Br	=1S1121: 300V			B300C300, etc
1S1124	Si-Br	=1S1121: 400V			B400C300, etc
1S1125	Si-Br	=1S1121: 600V			B600C300, etc
1S1126	Si-Br	=1S1121: 800V			B800C300, etc.
1S1127	Si-Br	=1S1121: 1000V			B1000C300, etc.
1S1128	Si-Br	Gl, 100V, 0,3A		Org	B100C300, etc.
1S1129	Si-Br	=1S1128: 200V			B200C300, etc.
1S112[Japan]	Si-Di	=1S111[Japan]: 200V	34a	Nec	BY126..127, BY133..134, 1N4003..07, ++
1S112[Texas]	Si-Di	=1S111[Texas]: 300V	31a	Tix	BA157..159, BY204/4, 1N4004..07, ++
1S1130	Si-Br	=1S1128: 300V			B300C300, etc.
1S1131	Si-Br	=1S1128: 400V			B400C300, etc.
1S1132	Si-Br	=1S1128: 600V			B600C300, etc.
1S1133	Si-Br	=1S1128: 800V			B800C300, etc.
1S1134	Si-Br	=1S1128: 1000V			B1000C300, etc.
1S1135	Si-Br	Gl, 100V, 1A		Org	B100C1000, etc.
1S1136	Si-Br	=1S1135: 200V			B200C1000, etc.
1S1137	Si-Br	=1S1135: 300V			B300C1000, etc.
1S1138	Si-Br	=1S1135: 400V			B400C1000, etc.
1S1139	Si-Br	=1S1135: 600V			B600C1000, etc.
1S113[Japan]	Si-Di	=1S111[Japan]: 300V	34a	Nec	BY126..127, BY133..134, 1N4004..07, ++
1S113[Texas]	Si-Di	=1S111[Texas]: 400V	31a	Tix	BA157..159, BY204/4, 1N4004..07, ++
1S1140	Si-Br	=1S1135: 800V			B8+F702600C1000, etc.
1S1141	Si-Br	=1S1135: 1000V			B1000C1000, etc.
1S1144	Si-Di	S, 90V, 0,4A, <20ns	2c	Oki	BAV14..18
1S1145	Si-Di	S, 90V, 0,9A, <20ns	34a	Oki	—
1S1146	Si-Di	SS, 40V, 0,1A, <6,9ns	31a	Hit	BAW62, BAX95, 1N4148..49, 1N4151, ++
1S1147	Si-Di	SS, 40V, 0,045A, <8,9ns	31a	Hit	BAW62, BAX95, 1N4148..49, 1N4151, ++
1S1148	Si-Di	SS, 60V, 0,25A, <7ns	31a	Oki	BAW62, BAX95, 1N4148..49, 1N4151, ++
1S1149	Si-Di	SS, 70V, 0,25A, <7ns	31a	Oki	BAW62, BAX95, 1N4148..49, 1N4151, ++
1S114[Japan]	Si-Di	=1S111[Japan]: 400V	34a	Nec	BY126..127, BY133..134, 1N4004..07, ++
1S1150	Si-Di	Gl-L, 400V, 280A(Tc=110°)	73b	Fjd	—
1S1151	Si-Di	=1S1150: 600V	73b		—
1S1152	Si-Di	=1S1150: 1000V	73b		—
1S1153	Si-Di	=1S1150: 1200V	73b		—
1S1154	Z-Di	6,3..7,7V, 0,1W	31	Nec	BZX55/.., BZX79/.., ZPD.., 1N5234..41, ++
1S1155	Z-Di	=1S1154: 7,5..9V	31		—
1S1156	Z-Di	=1S1154: 8,8..10,8V	31		—
1S115[Japan[	Si-Di	=1S111[Japan]: 500V	34a	Nec	BY126..127, BY133..134, 1N4005..07, ++
1S115[Texas]	Si-Di	=1S111[Texas]: 600V	31a	Tix	BA156..159, BY204/8, 1N4005..07, ++
1S1160	Z-Di	3..4,5V, 0,2W	31a	Nec	BZX55/.., BZX79/.., ZPD.., 1N5225..60, ++
1S1161	Z-Di	=1S1160: 4,3..5,4V	31a		—
1S1162	Z-Di	=1S1160: 5,2..6,4V	31a		—
1S1163	Z-Di	=1S1160: 6,2..8V	31a		—
1S1164	Z-Di	=1S1160: 7,5..10V	31a		—
1S1165	Z-Di	=1S1160: 9..12V	31a		—
1S1166	Z-Di	=1S1160: 11..14,5V	31a		—
1S1167	Z-Di	=1S1160: 13,5..18V	31a		—
1S1168	Z-Di	=1S1160: 17..21V	31a		—

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1S1169	Z-Di	=1S1160: 20..27V	31a		—
1S116[Japan}	Si-Di	=1S111[Japan]: 600V	34a	Nec	BY126..127, BY133..134, 1N4005..07,++
1S1170	Z-Di	=1S1160: 25..32V	31a		—
1S1171	Z-Di	=1S1160: 30..42V	31a		—
1S1172	Z-Di	4,3..5,4V, 1W	34	Nec	BZW22/.., BZX61/.., ZPY.., 1N5916..43,++
1S1173	Z-Di	=1S1172: 5,2..6,4V	34		—
1S1174	Z-Di	=1S1172: 6,2..8V	34		—
1S1175	Z-Di	=1S1172: 7,5..10V	34		—
1S1176	Z-Di	=1S1172: 9..12V	34		—
1S1177	Z-Di	=1S1172: 11..14,5V	34		—
1S1178	Z-Di	=1S1172: 13,5..16V	34		—
1S1179	Z-Di	=1S1172: 17..21V	34		—
1S117[Japan[	Si-Di	=1S111[Japan]: 700V	34a	Nec	BY127, BY133, BY227, 1N4006..07,++
1S117[Texas]	Si-Di	=1S111[Texas]: 800V	31a	Tix	BA159, BY204/8, 1N4006..07,++
1S1160	Z-Di	=1S1172: 20..27V	34		—
1S1181	Z-Di	=1S1172: 25..32V	34		—
1S1182	Z-Di	=1S1172: 30..40V	34		—
1S1183	Z-Di	=1S1172: 38,5..47,5V	34		—
1S1184	Z-Di	=1S1172: 45,5..57V	34		—
1S1185	Z-Di	4,3..5,4V, 3W	32	Nec	BZX98/.., BZY93.., ZX.., 1N2970..99
1S1186	Z-Di	=1S1185: 5,2..6,4V	32		—
1S1167	Z-Di	=1S1185: 6,2..8V	32		—
1S1186	Z-Di	=1S1185: 7,5..10V	32		—
1S1189	Z-Di	=1S1165: 9..12V	32		—
1S118[Japan}	Si-Di	=1S111[Japan]: 800V	34a	Nec	BY127, BY133, BY227, 1N4006..07,++
1S1190	Z-Di	=1S1185: 11..14,5V	32		—
1S1191	Z-Di	=1S1185: 13,5..18V	32		—
1S1192	Z-Di	=1S1185: 17..21V	32		—
1S1193	Z-Di	=1S1185: 20..27V	32		—
1S1194	Z-Di	=1S1185: 25..32V	32		—
1S1195	Z-Di	=1S1185: 30..40V	32		—
1S1195	Z-Di	=1S1185: 38,5..47,5V	32		—
1S1197	Z-Di	=1S1185: 49,5..57V	32		—
1S1198(A)	Ge-Di	Tunnel-Di, SS	≈31	Nec	—
1S1189(A)	Ge-Di	Tunnel-Di, SS	≈31	Nec	—
1S119[Japan}	Si-Di	=1S111[Japan]: 50V	34a	Nec	BY126..127, BY133..135, 1N4001..07,++
1S12	Ge-Di	Dem, 22,5V, 50mA	31a	Mat	AA112..114, 1N34, 1N54, 1N60,++
1S1200(A)	Ge-Di	Tunnel-Di, SS	≈31	Nec	—
1S1201(H)	Z-Di	5,9..8,5V, 0,25W	31	Hit	—
1S1202(H)	Z-Di	=1S1201: 8,2..8V	31		—
1S1203	Ref-Di	8..8,8V		Hit	—
1S1207	Si-Di	Gl-L, contr.av., 1000V, 10A(Tc=120°)	32a	Nec	1N4510..11
1S1208	Si-Di	Uni, 100V, 0,2A	31a	Nec	BA186..190, BAY19..21, BAY45..46,++
1S1209	Si-S1	0,83+C7078..0,69V(10mA), 0,1W	31a	Nec	BA220, BZ102/0V7, BZX55/C0V8, ZPD1
1S120[Japan[	Si-Di	Gl, 50V, 0,6A	34a	Nec	BY126..127, BY133..135, 1N4001..07,++
1S120[Texas]	Si-Di	Gl, 50V, 0,2A	31a	Tix	BA157..159, BY204/4, BY208..207,++
1S1210	Si-St	0,56..0,61V(1,5mA), 0,06W	31a	Nec	—
1S1211	Si-S1	0,59..0,64V(1,5mA), 0,06W	31a	Nec	—
1S1212	Si-St	0,82..0,87V(1,5mA), 0,06W	31a	Nec	BA220, BZ102/0V7, BZX55/C0V8, ZPD1
1S1213	Ge-Di	S, Uni, 50V, 0,06A, <250ns	31a	Nec	AAZ15, AAZ17, 1N276
1S1214	Ge-Di	S, Uni, 50V, 0,06A, <250ns	31a	Nec	AAZ15, AAZ17, 1N278
1S1215	Ge-Di	S, Uni, 40V, 0,06A, <200ne	31a	Nec	AAZ15, AAZ17, 1N276
1S1216	Ge-Di	S, Uni, 30V, 0,06A, <150ns	31a	Nec	AAZ15, AAZ17, 1N276
1S1217	Ge-Di	S, Uni, 75V, 0,1A, <750ne	31a	Nec	AAZ15
1S1218	Ge-Di	S, Uni, 100V, 0,1A, <750ns	31a	Nec	AAZ15
1S1219(H)	Si-Di	SS, 30V, 0,1A, <4ns	31a	Hit	BA317, BAY71, 1N4148..49, 1N4151,++
1S121[Japan]	Si-Di	=1S120[Japan]: 100V	34a	Nec	BY126..127, BY133..135, 1N4002..07,++
1S121[Texas]	Si-Di	=1S120[Texas]: 150V	31a	Tix	BA157..159, BY204/4, BY208..207,++
1S1220(H)	Si-Di	SS, 30V, 0,3A, <4ns	31a	Hit	BAW76
1S1221	Si-Di	Gl, Uni, 200V, 0,5A	31a	Shi	BY126..127, BY133..134, 1N4003..07,++
1S1222	Si-Di	=1S1221: 800V	31a		BY126..127, BY133..134, 1N4005..07,++
1S1223	Si-Di	=1S1221: 1000V	31a		BY127, BY133, BY227, 1N4007,++
1S1224	Si-Di	Gl, Uni, 800V, 0,1A	31a	Shi	BA158..159, BAY89..91, BY203/12,++
1S1225	Si-Di	=1S1224: 800V	31a		BA158..159, BAY90..91, BY203/12,++
1S1225A	Si-Di	=1S1224: 1000V	31a		BA159, BAY90..91, BY203/12, SHG1,++
1S1225	Si-Di	=1S1224: 1500V	31a		BAY91, BY203/16, BY584, SHG1,5,++

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1S 122[Japan]	Si-Di	=1S120[Japan]: 200V	34a	Nec	BY 126..127, BY 133..134, 1N4003..07,++
1S 1230(H,N)	Si-Di	Gl, Uni, 400V, 0,5A	34	Hit	BY 126..127, BY 133..134, 1N4004..07,++
1S 1231(H,N)	Si-Di	=1S1230: 500V	34		BY 126..127, BY 133..134, 1N4005..07,++
1S 1232(H,N)	Si-Di	=1S1230: 600V	34		BY 126..127, BY 133..134, 1N4005..07,++
1S 1233(H,N)	Si-Di	=1S1230: 600V	34		BY 127, BY 133, BY 227, 1N4006..07,++
1S 1234(H,N)	Si-Di	=1S1230: 1000V	34		BY 127, BY 133, BY 227, 1N4007,++
1S 1235	Z-Di	75..90V, 1W	34	Hit	BZW22/C82, BZX61/C82, ZPY82, 1N5947,++
1S 1236	Diac	Ub=18..32V, Ib<0,2mA, Itsm=2A	31l	Tos	1N5760, N413L, D3202U
1S 1237	Si-Di	Uni, S, 300V, 0,01A, <1,8µs	31a	Tos	BA 147/300, BAY21, BAY46, BAY88,++
1S 1238	Si-Di	=1S1237: 500V	31a		BA 158..159, BAY89..90, BAY92,++
1S 1239	Ge-Di	Dem, 25V, 0,03A	31a	Njr	AA 113..114, AA119, 1N34, 1N54, 1N60,++
1S 123[Japan]	Si-Di	=1S120[Japan]: 300V	34a		BY 126..127, BY 133..134, 1N4004..07,++
1S 1240	Ge-Di	AFC	31a	Njr	—
1S 1241	Ge-Di	AFC	31a	Njr	—
1S 1242	Ge-Di	AFC	31a	Njr	—
1S 1243	Ge-Di	AFC	31a	Njr	—
1S 1244	Ge-Di	Dem, 22,5V, 0,05A	31a	Mat	AA 112..114, AA119, 1N34, 1N54, 1N60,++
1S 1245	Ge-Di	Uni, 115V, 0,05A	31a	Mat	AA 117..118, AA 132..133, 1N634..35
1S 1246	Ge-Di	Uni, 115V, 0,05A	31a	Mat	AA 117..118, AA 132..133, 1N634..35
1S 1247	Si-Di	Gl-L, 500V, 200A(Tc=100°)	73b	Hit	—
1S 1248	Si-Di	=1S247: 600V	73b		—
1S 1249	Si-Di	=1S247: 600V	73b		—
1S 124[Japan]	Si-Di	=1S120[Japan]: 400V	34a		BY 126..127, BY 133..134, 1N4004..07,++
1S 1250	Si-Di	=1S247: 1000V	73b		—
1S 1251	Si-Di	=1S247: 1300V	73b		—
1S 125[Japan]	Si-Di	=1S120[Japan]: 500V	34a		BY 126..127, BY 133..134, 1N4005..07,++
1S 1260	Si-Di	Gl-L, 150V, 3A	32a	Tos	BYX 38/300, BYX 39/600
1S 1260R..1269R	Si-Di	=1S1260..1269:	32b		BYX38/..R, BYX39/..R
1S 1261	Si-Di	=1S1260: 200V	32a		BYX 38/300, BYX 39/600
1S 1262	Si-Di	=1S1260: 300V	32a		BYX 38/300, BYX 39/600
1S 1263	Si-Di	=1S1260: 400V	32a		BYX 38/600, BYX39/600
1S 1264	Si-Di	=1S1260: 500V	32a		BYX 38/600, BYX39/600
1S 1265	Si-Di	=1S1260: 600V	32a		BYX 38/600, BYX 39/600
1S 1266	Si-Di	=1S1260: 700V	32a		BYX 38/900, BYX 39/600
1S 1267	Si-Di	=1S1260: 600V	32a		BYX38/900, BYX39/800
1S 1268	Si-Di	=1S1260: 900V	32a		BYX 38/900, BYX39/1000
1S 1269	Si-Di	=1S1280: 1000V	32a		BYX38/1200, BYX39/1000
1S 126[Japan]	Si-Di	=1S+C7182120[Japan]: 600V	34a		BY 126..127, BY 133..134, 1N4005..07,++
1S 127	Ge-Di	Uni, 75V, 30mA	31	Tos	AA 117..118, AA 132..133, 1N634
1S 1270	Si-Di	Gl-L, 150V, 6A	32a	Tos	BYX 38/300, BYX 39/600
1S1270R..1279R	Si-Di	=1S1270..1279:	32b		BYX38/..R, BYX 39/..R
1S 1271	Si-Di	=1S1270: 200V	32a		BYX38/300, BYX39/600
1S 1272	Si-Di	=1S1270: 300V	32a		BYX38/300, BYX39/600
1S 1273	Si-Di	=1S1270: 400V	32a		BYX38/600, BYX39/600
1S 1274	Si-Di	=1S1270: 500V	32a		BYX38/600, BYX 39/600
1S 1275	Si-Di	=1S1270: 600V	32a		BYX38/600, BYX 39/600
1S 1276	Si-Di	=1S1270: 700V	32a		BYX38/900, BYX 39/600
1S 1277	Si-Di	=1S1270: 600V	32a		BYX 38/900, BYX 39/600
1S 1278	Si-Di	=1S1270: 900V	32a		BYX 38/900, BYX39/1000
1S 1279	Si-Di	=1S1270: 1000V	32a		BYX38/1200, BYX39/1000
1S 126	Ge-Di	S, 8V, <25ns	31a	Tos	AAY48, 1N995
1S 1280	Si-Di	Gl-L, 200V, 10A	32a	Hit	1N4525..30
1S 1260R..1285R	Si-Di	=1S1260..1285	32b		D24/400C..1200C
1S 1261	Si-Di	=1S1260: 300V	32a		1N4526..30
1S 1262	Si-Di	=1S1260: 400V	32a		1N4526..30
1S 1283	Si-Di	=1S1260: 600V	32a		1N4527..30
1S 1284	Si-Di	=1S1260: 800V	32a		1N4528..30
1S 1285	Si-Di	=1S1280: 1000V	32a		1N4529..30
1S 1268	Si-Di	Gl-L, 100V, 15A(Tc=50°)	75a	Tos	1N3492..95
1S 1288R..1288R	Si-Di	=1S1288..1288:	75b		1N3492R..95R
1S 1287	Si-Di	Gl-L, 100V, 20A(Tc=50°)	75a	Tos	1N3492..95
1S 1288	Si-Di	Gl-L, 100V, 20A(Tc=50°)	75a	Tos	1N3492..95
1S 1289	Si-Di	Gl-L, 150V, 12A	32a	Tos	1N4525..30
1S 1269R..1292R	Si-Di	=1S1289..1292:	32b		D24/C400
1S 1290	Si-Di	=1S1269: 300V	32a		1N4526..30
1S 1291	Si-Di	Gl-L, 150V, 25A	32a	Tos	1N4525..30

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1S1292	Si-Di	=1S1291: 300V	32a		1N4526..30
1S1295	Si-Di	SS, 70V, 0,17A, <5ns	31	Oki	BAW62, BAX95, 1N4148..49, 1N4151, ++
1S1296	Si-Di	SS, 90V, 0,2A, <5ns	31	Oki	BAW62, BAX95, 1N4148..49, 1N4151, ++
1S1297	Si-Di	S, 70V, 0,4A, <12ns	2c	Oki	BAV14..16, BAW26..27
1S1298	Si-Di	S, 125V, 0,45A, <12ns	2c	Oki	BAV14..16
1S1299	Si-Di	S, 125V, 0,6A, <12ns	2c	Oki	BAV14..16
1S129[Japan]	Ge-Di	S, 50V, 0,1A, <240ns	31a	Tos	AAY49, AAZ15, AAZ17
1S13	Ge-Di	Dem, 45V, 35mA	31a	Mat	AA113, 1N34, 1N54, 1N60
1S1300	Si-St	Level shift, 1,65..2,2V(2mA)	31a	Hit, Nec, ++	—
1S1301	Si-Di	SS, 35V, 0,045A, <5,3ns	31a	Hit, Nec, ++	BAW62, BAX95, 1N4148..49, 1N4151, ++
1S1302	Si-Di	SS, 70V, 0,25A, <7ns	31a	Hit, Nec, ++	BAW62, BAX95, 1N4146..49, 1N4151, ++
1S1303	Si-Di	SS, 60V, 0,25A, <7ns	31a	Hit, Nec, ++	BAW62, BAX95, 1N4148..49, 1N4151, ++
1S1304	Si-Di	S, 125V, 0,5A, <20ns	2c	Hit, Nec, ++	BAV14..16
1S1305	Si-Di	S, 125V, 0,9A, <20ns	34a	Hit, Nec, ++	—
1S130[Japan]	Ge-Di	=1S129[Japan]: <340ns	31a	Tos	AAY49, AAZ15, AAZ17
1S130[Texas]	Si-Di	Uni, 50V, 0,2A	31a	Tix	BA157..159, BY204/4, BY206..207, ++
1S1314	Si-Di	Modulator-Di	31a	Tos	—
1S1315	C-Di	AFC	31a	Nec	BA124..125, BB119, 1S2790, 1SV50, ++
1S1316	Si-Di	GI, Uni, 40V, 0,1A	31a	Nec	BA147/50, BA167..190, 1N5606..09, ++
1S1317	Si-Di	=1S1316: 60V	31a		BA147/100, BA188..190, 1N5606..09, ++
1S1316	Si-Di	=1S1316: 125V	31a		BA147/150, BA189..190, 1N5606..09, ++
1S1319	Si-Di	=1S1316: 250V	31a		BA147/300, BA157..159, BAY21, ++
1S131[Japan]	Ref-Di	6..9,5V	≈34a	Tos	—
1S131[Texas]	Si-Di	=1S130[Texas]: 100V	31a	Tix	BA157..159, BY204/4, BY206..207, ++
1S1320	Si-Di	=1S1316: 400V	31a		BA157..159, BAY69..90, BY207, ++
1S1321	Si-Di	GI-L, 100V, 5A(Tc=120°)	32a	Nec	BYX38/300, BYX39/600
1S1322	Si-Di	=1S1321: 200V	32a		BYX38/300, BYX39/600
1S1323	Si-Di	=1S1321: 300V	32a		BYX38/300, BYX39/600
1S1324	Si-Di	=1S1321: 400V	32a		BYX38/600, BYX39/600
1S1325	Si-Di	=1S1321: 500V	32a		BYX38/600, BYX39/600
1S1326	Si-Di	=1S1321: 600V	32a		BYX38/600, BYX39/600
1S1327	Si-Di	=1S1321: 700V	32a		BYX38/900, BYX39/600
1S1326	Si-Di	=1S1321: 800V	32a		BYX38/900, BYX39/800
1S1329	Si-Di	=1S1321: 900V	32a		BYX39/1200, BYX39/1000
1S132[Japan]	Ref-Di	6..9,5V	≈34a	Tos	—
1S132[Texas]	Si-Di	=1S130[Texas]: 200V	31a	Tix	BA157..159, BY204/4, BY206..207, ++
1S1330	Si-Di	=1S1321: 1000V	32a		BYX38/1200, BYX39/1000
1S1331	Si-Di	GI-L, 200V, 500A(Tc=130°)	73a	Nec	—
1S1332	Si-Di	=1S1331: 400V	73a		—
1S1333	Si-Di	=1S1331: 600V	73a		—
1S1334	Si-Di	=1S1331: 800V	73a		—
1S1335	Si-Di	=1S1331: 1000V	73a		—
1S1336	Si-Di	=1S1331: 1200V	73a		—
1S1337	Si-Di	=1S1331: 1400V	73a		—
1S1336	Si-Di	=1S1331: 1600V	73a		—
1S1339	Si-Di	=1S1331: 1600V	73a		—
1S133]Japan]	Ref-Di	6..9,5V	≈34a	Tos	—
1S1340	Si-Di	=1S1331: 2000V	73a		—
1S1341	Si-Di	GI, Uni, 50V, 0,8A	34	Mit	BY126..127, BY133..134, 1N4001..07, ++
1S1342	Si-Di	=1S1341: 100V	34		BY126..127, BY133..134, 1N4002..07, ++
1S1343	Si-Di	=1S1341: 200V	34		BY126..127, BY133..134, 1N4003..07, ++
1S1344	Si-Di	=1S1341: 300V	34		BY126..127, BY133..134, 1N4004..07, ++
1S1345	Si-Di	=1S1341: 400V	34		BY126..127, BY133..134, 1N4004..07, ++
1S1346	Si-Di	=1S1341: 800V	34		BY126..127, BY133..134, 1N4005..07, ++
1S1347	Si-Di	=1S1341: 600V	34		BY127, BY133, BY227, 1N4006..07, ++
1S1346	Si-Di	=1S1341: 1000V	34		BY127, BY133, BY227, 1N4007, ++
1S1349	Si-Di	=1S1341: 1200V	34		BY127, BY133, BY227, GP10Q, ++
1S134[Japan]	Z-Di	3,8..5,4V, 0,25W	31a	Tos	BZX55/C4V7, BZX79/C4V7, ZPD4,7, 1N5230++
1S134[Texas]	Si-Di	=1S130[Texas]: 400V	31a	Tix	BA157..159, BY204/4, BY206..207, ++
1S1350	Si-Di	GI, 50V, 2A	≈32a	Hit	(BY205/100, BY229/200, BYX49/300, ++)
1S1351	Si-Di	=1S1350: 100V	≈32a		(BY205/100, BY229/200, BYX49/300, ++)
1S1352	Si-Di	=1S1350: 200V	≈32a		(BY205/200, BY229/200, BYX49/300, ++)
1S1353	Si-Di	=1S1350: 300V	≈32a		(BY205/400, BY229/400, BYX49/300, ++)
1S1354	Si-Di	=1S1350: 400V	≈32a		(BY205/400, BY229/400, BYX49/600, ++)
1S1355	Si-Di	=1S1350: 600V	≈32a		(BY205/600, BY229/600, BYX49/600, ++)
1S1356	Si-Di	=1S1350: 600V	≈32a		(BY205/8+F733800, BY229/800, BYX49/900, ++)

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1S1357	Si-Di	=1S1350: 1000V	≈32a		(BY205/1000, BY229/1000, BYX49/1200,++)
1S1358	Si-Di	=1S1350: 1200V	≈32a		(BY329/1000, BY359/1300, BYX49/1200,++)
1S1359(A)	Si-Di	Gl, Uni, 200V, 0,2A	31a	Stl	BY126..127, BY133..134, 1N4003..07,++
1S135[Japan]	Z-Di	=1S134[Japan]: 5,2..6,2V	31a	Tos	BZX55/C5V6, BZX79/C5V6, ZPD5,6, 1N5232++
1S1360(A)	Si-Di	=1S1359: 400V	31a		BY126..127, BY133..134, 1N4004..07,++
1S1361(A)	Si-Di	=1S1359: 600V	31a		BY126..127, BY133..134, 1N4005..07,++
1S1362(A)	Si-Di	=1S1359: 600V	31a		BY127, BY133, BY227, 1N4006..07,++
1S1363(A)	Si-Di	=1S1359: 1000V	31a		BY127, BY133, BY227, 1N4007,++
1S1364(A)	Si-Di	=1S1359: 1200V	31a		BY127, BY133, BY227, GP10Q,++
1S1365(A)	Si-Di	Gl, Uni, 200V, 0,5A	31a	Stl	BY126..127, BY133..134, 1N4003..07,++
1S1366(A)	Si-Di	=1S1365: 400V	31a		BY126..127, BY133..134, 1N4004..07,++
1S1367(A)	Si-Di	=1S1365: 600V	31a		BY126..127, BY133..134, 1N4005..07,++
1S1368(A)	Si-Di	=1S1365: 800V	31a		BY127, BY133, BY227, 1N4006..07,++
1S1369(A)	Si-Di	=1S1365: 1000V	31a		BY127, BY133, BY227, 1N4007,++
1S136[Japan]	Z-Di	=1S134[Japan]: 6,0..7,1V	31a	Tos	BZX55/C6V6, BZX79/C6V6, ZPD6,8, 1N5235++
1S136[Texas]	Si-Di	=1S130[Texas]: 600V	31a	Tix	BA158..159, BY204/8, BY207, ++
1S1370(A)	Si-Di	=1S1365: 1200V	31a		BY127, BY133, BY227, GP10Q,++
1S1371(A)	Z-Di	2..3,2V, 0,25W	31a	Stl	BZX55/.., BZX79/.., ZPD.., 1N5221..61,++
1S1372(A)	Z-Di	=1S1371: 3..4V	31a		—
1S1373(A)	Z-Di	=1S1371: 3,8..5V	31a		—
1S1374(A)	Z-Di	=1S1371: 4,8..6V	31a		—
1S1375(A)	Z-Di	=1S1371: 5,8..7V	31a		—
1S1376(A)	Z-Di	=1S1371: 6..8V	31a		—
1S1377(A)	Z-Di	=1S1371: 7,7..9,5V	31a		—
1S1378(A)	Z-Di	=1S1371: 8,5..11V	31a		—
1S1379(A)	Z-Di	=1S1371: 10,5..14,5V	31a		—
1S137[Japan]	Z-Di	=1S134[Japan]: 6,9..8,1V	31a	Tos	BZX55/C7V5, BZX79/C7V5, ZPD7,5, 1N5236++
1S1380(A)	Z-Di	=1S1371: 14..18V	31a		—
1S1381(A)	Z-Di	=1S1371: 17..23V	31a		—
1S1362(A)	Z-Di	=1S1371: 22..28V	31a		—
1S1363(A)	Z-Di	=1S1371: 27..33V	31a		—
1S1364(A)	Z-Di	=1S1371: 32..36V	31a		—
1S1365(A)	Z-Di	=1S1371: 37..48V	31a		—
1S1366(A)	Z-Di	2..3,2V, 0,5W	31a	Stl	BZV85/.., BZX85/.., ZPY.., 1N4726..58,++
1S1367(A)	Z-Di	=1S1366: 3..4V	31a		—
1S1388(A)	Z-Di	=1S1386: 3,8..5V	31a		—
1S1369(A)	Z-Di	=1S1386: 4,8..8V	31a		—
1S136[Japan]	Z-Di	=1S134[Japan]: 7,9..9,1V	31a	Tos	BZX55/C8V2, BZX79/C8V2, ZPD8,2, 1N5237++
1S136[Texas]	Si-Di	=1S130[Texas]: 800V	31a	Tix	BA159, BY204/8, BY208/600, ++
1S1390(A)	Z-Di	=1S1386: 5,8..7V	31a		—
1S1361(A)	Z-Di	=1S1388: 6,8..8V	31a		—
1S1392(A)	Z-Di	=1S1386: 7,7..9,5V	31a		—
1S1393(A)	Z-Di	=1S1386: 8,5..11V	31a		—
1S1394(A)	Z-Di	=1S1386: 10,5..14,5V	31a		—
1S1395(A)	Z-Di	=1S1386: 14..18V	31a		—
1S1366(A)	Z-Di	=1S1386: 17..23V	31a		—
1S1367(A)	Z-Di	=1S1386: 22..26V	31a		—
1S1398(A)	Z-Di	=1S1386: 27..33V	31a		—
1S1399(A)	Z-Di	=1S1386: 32..36V	31a		—
1S139[Japan]	Z-Di	=1S134[Japan]: 8,9..10,1V	31a	Tos	BZX55/C9V1, BZX79/C9V1, ZPD9,1, 1N5239++
1S14	Ge-Di	Dem, 45V, 35mA	31a	Mat	AA113, 1N34, 1N54, 1N60
1S1400(A)	Z-Di	=1S1366: 37..48V	31a		—
1S1401(A)	Z-Di	=1S1386: 47..58V	31a		—
1S1402	Z-Di	2..3,2V, 1W	34a	Stl	BZW22/.., BZX61/.., ZPY.., 1N5913..36,++
1S1402R...1415R	Z-Di	=1S1402..1415	34b		—
1S1403	Z-Di	=1S1402: 3..4V	34a		—
1S1404	Z-Di	=1S1402: 3,8..5V	34a		—
1S1405	Z-Di	=1S1402: 4,8..6V	34a		—
1S1406	Z-Di	=1S1402: 5,8..7V	34a		—
1S1407	Z-Di	=1S1402: 6,8..8V	34a		—
1S1408	Z-Di	=1S1402: 7,7..9,5V	34a		—
1S1408	Z-Di	=1S1402: 8,5..11V	34a		—
1S140[Japan]	Z-Di	=1S134[Japan]: 9,9..12,2V	31a	Tos	BZX55/C11, BZX79/C11, ZPD11, 1N5241,++
1S140[Texas]	Si-Di	Gl, 50V, 0,3A	31a	Tix	BA157..159, BY204/4, BY206..207,++
1S1410	Z-Di	=1S1402: 10,5..14,5V	34a		—
1S1411	Z-Di	=1S1402: 14..18V	34a		—

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1S1412	Z-Di	=1S1402: 17..23V	34a		—
1S1413	Z-Di	=1S1402: 22..28V	34a		—
1S1414	Z-Di	=1S1402: 27..33V	34a		—
1S1415	Z-Di	=1S1402: 32..38V	34a		—
1S1417	Si-Di	Gl, contr.av., 800V, 25A(Tc=135°)	32	Tos	1N4528..30
1S1418	Si-Di	=1S1417: 1000V	32		1N4529..30
1S1419	Si-Di	=1S1417: 1200V	32		1N4530
1S141[Japan]	Z-Di	=1S134[Japan]: 11,8..13,9V	31a	Tos	BZX55/C13, BZX79/C13, ZPD13, 1N5243,++
1S141[Texas]	Si-Di	=1S140[Texas]: 100V	31a	Tix	BA157..159, BY204/4, BY206..207,++
1S1420(H)	Si-St	Level shift, <2,2V(2mA), 0,1W	31a	Hit	—
1S1421(R)	Z-Di	=1S1402: 37..48V	34a/b		—
1S1422(R)	Z-Di	=1S1402: 47..58V	34a/b		—
1S1423	Z-Di	2..3,2V, 3W	32a	Stl	BZX98/.., BZY93/.., ZL.., 1N2970..99,++
1S1423R..1438R	Z-Di	=1S1423..1438:	32b		—
1S1424	Z-Di	=1S1423: 3..4V	32a		—
1S1425	Z-Di	=1S1423: 3,8..5V	32a		—
1S1426	Z-Di	=1S1423: 4,8..6V	32a		—
1S1427	Z-Di	=1S1423: 5,8..7V	32a		—
1S1428	Z-Di	=1S1423: 6,8..8V	32a		—
1S1429	Z-Di	=1S1423: 7,7..9,5V	32a		—
1S142[Japan[	Z-Di	=1S134[Japan[: 13,3..15,5V	31a	Tos	BZX55/C15, BZX79/C15, ZPD15, 1N5245,++
1S142[Texas]	Si-Di	=1S140[Texas]: 200V	31a	Tix	BA157..159, BY204/4, BY206..207,++
1S1430	Z-Di	=1S1423: 8,5..11V	32a		—
1S1431	Z-Di	=1S1423: 10,5..14,5V	32a		—
1S1432	Z-Di	=1S1423: 14..18V	32a		—
1S1433	Z-Di	=1S1423: 17..23V	32a		—
1S1434	Z-Di	=1S1423: 22..28V	32a		—
1S1435	Z-Di	=1S1423: 27..33V	32a		—
1S1436	Z-Di	=1S1423: 32..38V	32a		—
1S1437	Z-Di	=1S1423: 37..48V	32a		—
1S1438	Z-Di	=1S1423: 47..58V	32a		—
1S1439	Z-Di	3,8..5V, 10W	32a	Stl	BZX98/.., BZY93/.., ZL.., 1N2970..99,++
1S1439R..1452R	Z-Di	=1S1439..1452:	32b		—
1S143[Japan)	Z-Di	=1S134[Japan]: 14,7..17,3V	31a	Tos	BZX55/C16, BZX79/C16, ZPD16, 1N5246,++
1S1440	Z-Di	=1S1439: 4,8..6V	32a		—
1S1441	Z-Di	=1S1439: 5,8..7V	32a		—
1S1442	Z-Di	=1S1439: 6,8..8V	32a		—
1S1443	Z-Di	=1S1439: 7,7..9,5V	32a		—
1S1444	Z-Di	=1S1439: 8,5..11V	32a		—
1S1445	Z-Di	=1S1439: 10,5..14,5V	32a		—
1S1446	Z-Di	=1S1439: 14..18V	32a		—
1S1447	Z-Di	=1S1439: 17..23V	32a		—
1S1448	Z-Di	=1S1439: 22..28V	32a		—
1S1449	Z-Di	=1S1439: 27..33V	32a		—
1S144[Japan]	Si-Di	Meawerkschutz/meter protection	31a	Tos	—
1S144[Texas]	Si-Di	=1S140[Texas]: 400V	31a	Tix	BA157..159, BY204/4, BY206..207,++
1S1450	Z-Di	=1S1439: 32..38V	32a		—
1S1451	Z-Di	=1S1439: 37..48V	32a		—
1S1452	Z-Di	=1S1439: 47..58V	32a		—
1S1454	Si-Di	Gl-L, 400V, 6A(Tc=120°)	73a	Fjd	BYX42/600, BYX98/600
1S1455	Si-Di	=1S1454: 800V	73a		BYX42/900, BYX98/900
1S1456	Si-Di	=1S1454: 1000V	73a		BYX42/1200, BYX98/1200
1S1457	Si-Di	=1S1454: 1200V	73a		BYX42/1200, BYX98/1200
1S1458	Si-Di	SS, 60V, 0,1A, <2ns	31a		BAW62, BAX95, 1N4148..49, 1N4151,++
1S1459	Si-Di	SS, 60V, 0,15A, <2ns	31a		BAW62, BAX95, 1N4148..49, 1N4151,++
1S145[Japan]	C-Di	FM/VHF-AFC	31a	Tos	BA124..125, BB119, 1S2790, 1SV50,++
1S1460	Si-Di	SS, 60V, 0,35A, <2ns	31a		BAW76
1S1461	Si-Di	Gl-L, contr.av., 800V, 12A(Tc=135°)	32b	Tos	BYX25/800R
1S1462	Si-Di	=1S1461: 1000V	32b		BYX25/1000R
1S1463	Si-Di	=1S1461: 1200V	32b		BYX25/1200R
1S1464	Si-Di	UHF-M, 800MHz	31a	Say	—
1S1465	Ge-Di	TV-Damper-Di, 250V, 10A(ss)	22	Tos	—
1S1466	Si-Di	SS, 60V, 0,08A, <2ns	31a		BAW62, BAX95, 1N4148..49, 1N4151,++
1S1467	Si-Di	SS, 60V, 0,25A, <2ns	31a		BAW62, BAX95, 1N4148..49, 1N4151,++
1S146[Japan]	Si-Di	Gl, Uni, 100V, 0,6A	31a	Fui	BY126..127, BY133..135, 1N4002..07,++
1S1471	Si-Di	Gl, contr.av., 1000V, 1A	34a	Nec	BYV36E, BYV96E, BYW56, 1N4249

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1S1472	Si-Di	Gl,Uni,600V,0,15A	2b	Tos	BA158..159, BAY89..90, BY207,++
1S1473(H,K)	Si-Di	SS,30V,0,1A,<4ns	12c	Hit	BA318, BAY38, 1N4148..49, 1N4151,++
1S1474	Si-Di	Gl,contr.av.,200V,1,5A	34	Shi	BYV36A, BYV95A, BYW52..56, BYW95A
1S1475	Si-Di	=1S1474: 400V	34		BYV38B, BYV95B, BYW53..56, BYW95B
1S1476	Si-Di	=1S1474: 600V	34		BYV36C, BYV95C, BYW54..56, BYW95C
1S1477	Si-Di	=1S1474: 800V	34		BYV36D, BYV96D, BYW55..58, BYW96D
1S1478	Si-Di	=1S1474: 1000V	34		BYV36E, BYV96E, BYW56, BYW96E
1S1479	Si-Di	=1S1474: 1200V	34		SSiB9880A
1S147 [Japan]	Si-Di	=1S146[Japan]: 200V	31a		BY126..127, BY133..134, 1N4003..07,++
1S1480	Si-Di	Gl-L,200V,20A(Tc=90°)	73a	Shi	1N4525..30
1S1481	Si-Di	=1S1480: 400V	73a		1N4526..30
1S1482	Si-Di	=1S1480: 600V	73a		1N4527..30
1S1483	Si-Di	=1S1480: 800V	73a		1N4523..30
1S1484	Si-Di	=1S1480: 1000V	73a		1N4529..30
1S1485	Si-Di	=1S1480: 1200V	73a		1N4530
1S1486	Si-Di	Gl,contr.av.,100V,0,4A	31a	Shi	BYV36A, BYV95A, BYW52..56, BYW95A
1S1487	Si-Di	=1S1486: 200V	31a		BYV36A, BYV95A, BY+F7572W52..56, BYW95A
1S1488	Si-Di	Gl,Uni,200V,1,5A	34	Hit	BY226..227, BY251..255, 1N5393..99,++
1S1489	Si-Di	=1S1486: 400V	34		BY228..227, BY252..255, 1N5395..99,++
1S148 [Japan]	Si-Di	=1S146[Japan]: 300V	31a		BY128..127, BY133..134, 1N4004..07,++
1S1490	Si-Di	=1S1488: 600V	34		BY226..227, BY253..255, 1N5397..99,++
1S1491	Si-Di	=1S1486: 600V	34		BY227, BY254..255, 1N5398..99,++
1S1492	Si-Di	=1S1486: 1000V	34		BY227, BY255, BYW56, 1N5399,++
1S1493	Si-Di	Gl-L,200V,30A	32a	Hit	BYX56/600, BYX97/300
1S1493R..1495R	Si-Di	=1S1493..1495	32b		BYX56/..R, BYX97/..R
1S1494	Si-Di	=1S1493: 400V	32a		BYX56/600, BYX97/600,
1S1495	Si-Di	=1S1493: 600V	32a		BYX56/600, BYX97/600,
1S1496	Si-Di	Gl-L,200V,50A(Tc=70°)	73a	Hit	1N3289..97
1S1496R..1498R	Si-Di	=1S1496..1498	73b		1N3289R..97R
1S1497	Si-Di	=1S1496: 400V	73a		1N3291..97
1S1498	Si-Di	=1S1496: 600V	73a		1N3293..97
1S149 [Japan]	Si-Di	=1S146[Japan]: 400V	31a		BY126..127, BY133..134, 1N4004..07,++
1S15	Ge-Di	Dem,45V,35mA	31a	Mat	AA113, 1N34, 1N54, 1N60
1S1500	C-Di	AFC	31a	Njr	BA124..125, BB119, 1S2790, 1SV50,++
1S1501	C-Di	AFC	31a	Njr	BA124..125, BB119, 1S2790, 1SV50,++
1S1502	C-Di	AFC	31a	Njr	BA124..125, BB119, 1S2790, 1SV50,++
1S1503	C-Di	AFC	31a	Njr	BA124..125, BB119, 1S2790, 1SV50,++
1S150 [Japan]	Si-Di	=1S148[Japan]: 500V	31a		BY126..127, BY133..134, 1N4005..07,++
1S151	Si-Di	Gl-L,100V,1,5A	32a	Nec	BYX38/300, BYX39/600
1S1514(M)	Si-Di	SS,90V,0,12A,<2ns	31a	Tos	BA219, 1N4148..49, 1N4446..49,++
1S1515(M)	Si-Di	SS,55V,0,12A,<2ns	31a	Tos	BA219, 1N4148..49, 1N4446..49,++
1S1516(M)	Si-Di	SS,55V,0,12A,<2ns	31a	Tos	BA219, 1N4148..49, 1N4446..49,++
1S1517(A)	Si-Di	TV-Dampar-Di,1500V,0,5A	34a	Tos	BY228, BY269, BY400, BY448
1S1518	Si-Di	Gl-L,200V,10A	75a	Sak	1N3493..95
1S1518R...1522R	Si-Di	=1S1518..1522	75b		1N3493R..95R
1S1519	Si-Di	=1S1518: 400V	75a		1N3495
1S152	Si-Di	=1S151: 200V	32a		BYX38/300, BYX39/600
1S1520	Si-Di	=1S1518: 500V	75a		—
1S1521	Si-Di	=1S1518: 600V	75a		—
1S1522	Si-Di	=1S1518: 600V	75a		—
1S1523(R)	Si-Di	Gl-Array,200V,80A(Tc=75°)		Sak	—
1S1524(R)	Si-Di	=1S1528: 500V			—
1S1525(R)	Si-Di	=1S1528: 600V			—
1S1526	Si-Br	Gl,100V,0,6A		Sak	B100C600,atc.
1S1527	Si-Br	=1S1526: 200V			B200C600, etc.
1S1526	Si-Br	=1S1526: 400V			B400C600, atc.
1S1529	Si-Br	=1S1526: 600V			B600C600, etc.
1S153	Si-Di	=1S151: 300V	32a		BYX38/300, BYX39/800
1S1530	Si-Br	=1S1526: 800V			B800C600, etc
1S1531	Si-Br	=1S1526: 1000V			B1000C600, etc.
1S1532	Si-Di	SS,35V,0,06A,<4ns	31a	Sak	BA218, BAX13, BAX91, 1N4148..49,++
1S154	Si-Di	=1S151: 400V	32a		BYX38/600, BYX39/600
1S1540(N)	Z-Di	68..83V,35W(Tc=55°)	23	Tos	—
1S1541(N)	Z-Di	=1S1540: 77..103V	23		—
1S1542(N)	Z-Di	=1S1540: 103..115V	23		—
1S1543(N)	Z-Di	=1S1540: 140..186V	23		—

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1S 1544(A)	Si-Di	S, 30V, 0,1A, <100ns	31a	Nec	BAV 17. 21, BAX90, BAX94, BAY 41 .43++
1S 1545	Si-Di	S, 30V, 0,1A, <100ns	31a	Nec	BAV 17. 21, BAX90, BAX94, BAY 41..43++
1S 1546	Si-Di	Gl, Uni, 100V, 0,6A	31a	Tos	BY 126..127, BY 133..135, 1N4002..07,++
1S 1547	Si-Di	=1S1546: 200V	31a		BY 126..127, BY 133..134, 1N4003..07,++
1S 1548	Si-Di	=1S1546: 400V	31a		BY 126..127, BY 133..134, 1N4004..07,++
1S 1549	Si-Di	UHF-M, 890MHz	31a	Tos	—
1S 155	Si-Di	=1S151: 500V	32a		BYX 38/600, BYX 39/600
1S 1550	Z-Di	=1S1540: 162..195V	23		—
1S 1551	Si-Di	Varaktor, HF-Multipl	32a	Tos	—
1S 1552	Si-Di	Varaktor, HF-Multipl	32a	Tos	—
1S 1553	Si-Di	Dem, Uni, 70V, 0,1A	31a	Tos	BA 147/100, BA 188..190, 1N5606..09, ++
1S 1554	Si-Di	=1S1553: 55V	31a		BA 147/100, BA 188..190, 1N5606..06, ++
1S 1555	Si-Di	=1S1553: 35V	31a		BA 147/50, BA 187..190, 1N5606..09, ++
1S 1556	Si-Di	Varaktor, HF-Multipl	32a	Tos	—
1S 1557	Si-Di	Varaktor, HF-Multipl	32a	Tos	—
1S 1558	Si-Di	Varaktor, HF-Multipl	32a	Tos	—
1S 156	Si-Di	=1S151: 600V	32a		BYX 38/600, BYX 39/600
1S 1580(R)	Si-Di	Gl, 100V, 3A(Tc=120°)		Tos	(BY 205/200, BY 229/200, BYX 49/300,++)
1S 1581	Si-Di	Varaktor, HF-Multipl	Koax	Tos	—
1S 1582	Si-Di	Varaktor, HF-Multipl	Koax	Tos	—
1S 1563	Si-Di	Varaktor, HF-Multipl	Koax	Tos	—
1S 1564	Si-Di	Varaktor, HF-Multipl	Koax	Tos	—
1S 1585	Si-Di	Gl-L, 600V, 350A(Tc=90°)	≈73	Tos	—
1S 1566	Si-Di	=1S1565: 1000V	≈73		—
1S 1567	Si-Di	=1S1565: 1200V	≈73		—
1S 1566	Si-Di	=1S1565: 1500V	≈73		—
1S 1569	Si-Di	=1S1565: 1600V	≈73		—
1S 157	Si-Di	Gl-L, 100V, 1A	32a	Nec	BYX 38/300, BYX 39/600
1S 1570	Si-Di	=1S1585: 2000V	≈73		—
1S 1571	Si-Di	Varaktor, HF-Multipl	Koax	Tos	—
1S 1572	Si-Di	Varaktor, HF-Multipl	Koax	Tos	—
1S 1573	Si-Di	Varaktor, HF-Multipl	Koax	Tos	—
1S 1574	Si-Di	Varaktor, HF-Multipl	Koax	Tos	—
1S 1575	Si-Di	Gl-L, 400V, 12A(Tc=120°)	32	Tos	1N4526..30
1S 1576	Si-Di	=1S1575: 600V	32		1N4527..30
1S 1577	Si-Di	=1S1575: 800V	32		1N4528..30
1S 1578	Si-Di	=1S1575: 1000V	32		1N4529..30
1S 1579	C-Di	Dual, TV-AFC (Horiz.-O), 60V, 0,05A	7e	Tos	—
1S 158	Si-Di	=1S157: 200V	32a		BYX 38/300, BYX 39/600
1S 1580	C-Di	=1S1579: 35V	7e		—
1S 1581	Si-Di	Varaktor, 10GHz	Koax	Tos	—
1S 1582	C-Di	AFC	31a	Tos	BA 124..125, BB119, 1S2790, 1SV50, ++
1S 1583	Si-Di	Varaktor	32	Tos	—
1S 1565	Si-Di	SS, 90V, 0,15A, <2ns	31a	Tos	BAW62, BAX95, 1N4148..49, 1N4151, ++
1S 1566	Si-Di	SS, 55V, 0,15A, <2ns	31a	Tos	BAW62, BAX95, 1N4148..49, 1N4151, ++
1S 1587	Si-Di	SS, 55V, 0,13A, <2ns	31a	Tos	BAW62, BAX95, 1N4148..49, 1N4151, ++
1S 1566	Si-Di	SS, 35V, 0,12A, <4ns	31a	Tos	BAW62, BAX95, 1N4148..49, 1N4151, ++
1S 1589	Si-Di	SS, 40V, 0,06A, <4ns	31a	Sak	BA 218, BAX 13, BAY 71, 1N4148..49, ++
1S 159	Si-Di	=1S157: 300V	32a		BYX 38/300, BYX 39/600
1S 1591	Si-Di	Gl, S, 600V, 0,03A, <300ns	31a	SAk	BA156..159, BY 203/12, SHG 1, ++
1S 1592	Si-Di	=1S1591: 600V	31a		BA 159, BY 203/12, BY 268..269, SHG 1, ++
1S 1593	Si-Di	=1S1591: 1000V	31a		BA 159, BY 203/12, BY 288..269, SHG 1, ++
1S 1594	Si-Di	=1S1591: 1200V	31a		BY 203/12, BY 268..269, SHG 1,5, ++
1S 1595	Si-Di	=1S1591: 1500V	31a		BY 203/16, BY 269, SHG 1,5
1S 1596	Si-Di	=1S1591: 1600V	31a		BY 203/20, SHG2
1S 1597	Si-Di	Gl, Uni, 35V, 0,1A	31a	Hit	BA 147/50, BA 187..190, 1N5606..09, ++
1S 1596	Si-Di	=1S1597: 50V	31a		BA 147/50, BA 187..190, 1N5606..06, ++
1S 1599	Si-Di	=1S1597: 100V	31a		BA 147/100, BA 188..190, 1N5606..07, ++
1S 16	Ge-Di	Dem, 45V, 35mA	31a	Mat	AA 113, 1N34, 1N54, 1N60
1S 160	Si-Di	Gl-L, 50V, 10A(Tc=120°)	32a	Nec	BYX 42/300, BYX 98/300
1S 1600	Si-Di	=1S1597: 200V	31a		BA 147/230, BA 190, BAY 21, BAY 88..90++
1S 1601	Si-Di	=1S1597: 300V	31a		BA 147/300, BAY 21, BAY 88..90, ++
1S 1602	Si-Di	=1S1597: 400V	31a		BA 157..159, BAY69..90, BY 207, ++
1S 1604	Si-Di	Gl, Uni, 100V, 1,1A	31a	Hit	BY 126..127, BY 133..135, 1N4002..07,++
1S 1605	Si-Di	Gl, Uni, 600V, 0,5A	31a	Hit	BY 127, BY 133, BY 227, 1N4006..07,++
1S 1606	Si-Di	Gl-L, 200V, 20A(Tc=100°)	32a	Hit	1N4525..30

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1S1606R..1607R	Si-Di	=1S1606..1607:	32b		D24/400C
1S1607	Si-Di	=1S1606: 300V	32a		1N4526..30
1S1608	Si-Di	GI, Uni, 1000V, 0,5A	31a	Hit	BY127, BY133, BY227, 1N4007, ++
1S1609	Si-Di	=1S1608: 1300V	31a		BY127, BY133, BY227, GP10V, ++
1S161	Si-Di	=1S160: 100V	32a		BYX42/300, BYX98/300
1S1610	Si-Di	=1S1608: 1500V	31a		BY269, DM513, EM516, GP10W
1S1611	Si-Di	kV-GI, 6kV, 0,06A	31a	Isi	1N5183
1S1612	Si-Di	=1S1611: 12kV	31a		1N3052
1S1813	Si-Di	=1S1611: 16kV	31a		1N3055
1S1614	Si-Di	GI-L, 800V, 50A(Tc=135°)	73b	Tos	1N3294R..97R
1S1615	Si-Di	=1S1614: 1000V	73b		1N3295R..97R
1S1616	Si-Di	=1S1614: 1200V	73b		1N3296R..97R
1S1617	C-Di	FM/VHF-AFC	31a	Nec	BA111, BA124, 1S2790, 1SV50, ++
1S1618	C-Di	FM/VHF-AFC	31a	Nec	BA111, BA124, 1S2790, 1SV50, ++
1S1619	C-Di	FM/VHF-AFC	31a	Nec	BA111, BA124, 1S2790, 1SV50, ++
1S162	Si-Di	=1S160: 200V	32a		BYX42/300, BYX98/300
1S1620	Si-Di	SS, 50V, 0,115A, <4ns	31a	Mat	BAW62, BAX95, 1N4148..49, 1N4151, ++
1S1621	Si-Di	S, 175V, 0,1A, <400ns	31a	Tos	BA195, BAX15, BAX17, 1N3070, ++
1S1622	Si-Di	GI, Uni, 100V, 0,3A	31a	Tos	BA157..159, BY204/4, BY206..207, ++
1S1623	Si-Di	=1S1622: 200V	31a		BA157..159, BY204/4, BY206..207, ++
1S1624	Si-Di	=1S1622: 400V	31a		BA157..159, BY204/4, BY207, ++
1S1625	Si-Di	=1S1622: 800V	31a		BA158..159, BY204/8, BY207, ++
1S1626	Si-Di	GI-L, contr.av., 800V, 6A(Tc=135°)	32	Tos	1N4509..11
1S1627	Si-Di	=1S1626: 1000V	32		1N4510..11
1S1628	Si-Di	=1S1626: 1200V	32		1N4511
1S1629	Si-Di	GI-L contr.av., 800V, 3A(Tc=135°)	32	Tos	BYX39/800
1S163	Si-Di	=1S160: 300V	32a		BYX42/300, BYX98/300
1S1630	Si-Di	=1S1629: 1000V	32		BYX39/1000
1S1631	Si-Di	=1S1629: 1200V	32		BYX39/1200
1S1632	Si-Di	GI-L, 150V, 150A(Tc=110°)	73	Tos	1N4588..4596
1S1633	Si-Di	=1S1632: 300V	73		1N4589..4596
1S1634	Si-Di	=1S1632: 400V	73		1N4590..4596
1S1635	Si-Di	=1S1632: 500V	73		1N4591..4596
1S1636	Si-Di	=1S1632: 600V	73		1N4592..4596
1S1637	Si-Di	=1S1632: 700V	73		1N4593..4596
1S1638	Si-Di	=1S1632: 800V	73		1N4593..4596
16 1639	Si-Di	=1S1632: 1000V	73		1N4594..4596
1S164	Si-Di	=1S160: 400V	32a		BYX42/600, BYX98/600
1S1640(R)	Si-Di	GI-L, 100V, 15A(Tc=120°)		Tos	(BYX25/600, BYX99/300)
1S1641(R)	Si-Di	GI-L, 100V, 20A(Tc=120°)		Tos	(BYX25/600)
1S1642	Si-Di	GI-L, 400V, 25A(Tc=90°)	32a		1N4526..30
1S1642R	Si-Di	=1S1642:	32b	Tos	D24/400C
1S1643	Si-Di	GI-L, 150V, 50A(Tc=120°)	73a	Tos	1N3289..97
1S1643R..1644R	Si-Di	=1S1643..1644:	73b		1N3289R..97R
1S1644	Si-Di	=1S1643: 300V	73a		1N3290..97
1S1645	Si-Di	GI-L, 150V, 100A(Tc=110°)	73a	Tos	1N3289..97
1S1645R..1646R	Si-Di	=1S1645..1646:	73b		1N3289R..97R
1S1646	Si-Di	=1S1645: 300V	73a		1N3290..97
1S1647	Si-Di	GI-L, 150V, 200A(Tc=100°)	73a	Tos	1N3736..44
1S1647R..1648R	Si-Di	=1S1647..1648:	73b		1N3736R..44R
1S1646	Si-Di	=1S1647: 300V	73a		1N3737..44
1S165	Si-Di	=1S160: 500V	32a		BYX42/600, BYX98/600
1S1650	C-Di	AFC	31a	Tos	BA124..125, BB119, 1S2790, 1SV50, ++
1S1651	C-Di	AFC	31a		BA124..125, BB119, 1S2790, 1SV50, ++
1S1652	Si-Di	GI-L, 150V, 12A(Tc=50°)	32a	Tos	1N4525..30
1S1652R..1653R	Si-Di	=1S1652..1653:	32b		D24/400C
1S1653	Si-Di	=1S1652: 300V	32a		1N4526..30
1S1654	Si-Di	GI-L, 150V, 25A(Tc=50°)	32a	Tos	1N4525..30
1S1654R..1655R	Si-Di	=1S1654..1655:	32b		D24/400C
1S1655	Si-Di	=1S1654: 300V	32a		1N4526..30
1S1656	Ge-Di	TV-Damper-Di, 150V, 6A(Tc=50°)	22	Hit	—
1S1657	Ge-Di	=1S1656: 200V	22		—
1S1658	C-Di	FM-AFC	31a	Tos	BA111, BA124, 1S2790, 1SV50, ++
1S1659	Si-Di	SS, 10V, 0,05A, <1ns	31a	Nec	BAY62, 1N4244, 1N4376
1S166	Si-Di	=1S160: 800V	32a		BYX42/600, BYX98/800
1S1660	Si-Di	GI-L, 150V, 3A	32a	Tos	BYX38/300, BYX39/900

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1S1660R..1661R	Si-Di	=1S1660..1661:	32b		BYX38/300R, BYX39/900R
1S1661	Si-Di	=1S1660: 300V	32a		BYX38/300, BYX39/900
1S1662	Si-Di	Gl-L, 150V, 6A	32a	Tos	BYX38/300, BYX39/900
1S1662R..1663R	Si-Di	=1S1662..1663:	32b		BYX38/300R, BYX39/900R
1S1663	Si-Di	=1S1662: 300V	32a		BYX38/300, BYX39/900
1S1664	Si-Di	Gl, Uni, 100V, 1A	31a	Inr	BY126..127, BY133..135, 1N4002..07,++
1S1665	Si-Di	=1S1664: 200V	31a		BY126..127, BY133..134, 1N4003..07,++
1S1666	Si-Di	=1S1664: 400V	31a		BY126..127, BY133..134, 1N4004..07,++
1S1667	Si-Di	=1S1664: 600V	31a		BY126..127, BY133..134, 1N4005..07,++
1S1666	Si-Di	=1S1664: 600V	31a		BY127, BY133, BY227, 1N4006..07,++
1S1669	Si-Di	=1S1664: 1000V	31a		BY127, BY133, BY227, 1N4007,++
1S167	Si-Di	Gl-L, 100V, 5A(Tc=120°)	32a	Nec	BYX38/300, BYX39/600
1S1670	Si-Br	Gl, 100V, 1,8A	42	Inr	B100C2000, etc.
1S1671	Si-Br	=1S1670: 200V	42		B200C2000, etc.
1S1672	Si-Br	=1S1670: 400V	42		B400C2000, etc.
1S1673	Si-Br	=1S1670: 600V	42		B600C2000, etc.
1S1674	Si-Br	=1S1670: 600V	42		B600C2000, etc.
1S1675	Si-Br	=1S1670: 1000V	42		B1000C2000, etc.
1S1676	Ge-Di	Tunnel-Di	Koax	Nec	—
1S1677	Ge-Di	Tunnel-Di	Koax	Nec	—
1S1676	Si-Di	Gl, Uni, 100V, 1,3A	34	Inr	BY251..255, BY226..227, 1N5392..99,++
1S1679	Si-Di	=1S1678: 200V	34		BY251..255, BY226..227, 1N5393..99,++
1S166	Si-Di	=1S167: 200V	32a		BYX38/300, BYX39/600
1S1660	Si-Di	=1S1676: 400V	34		BY252..255, BY226..227, 1N5395..99,++
1S1681	Si-Di	=1S1676: 600V	34		BY253..255, BY226..227, 1N5397..99,++
1S1662	Si-Di	=1S1676: 600V	34		BY254..255, BY227, 1N5396..99,++
1S1663	Si-Di	=1S1676. 1000V	34		BY255, BY227, BYW56, 1N5399,++
1S1664	Si-Di	=1S1676	34a		→1S1676
1S1665	Si-Di	=1S1679	34a		→1S1679
1S1686	Si-Di	=1S1680	34a		→1S1680
1S1687	Si-Di	=1S1661	34a		→1S1661
1S1686	Si-Di	=1S1682	34a		→1S1682
1S1669	Si-Di	=1S1663	34a		→1S1663
1S169	Si-Di	=1S167: 300V	32a		BYX38/300, BYX39/600
1S1690(A)	Si-Di	Gl, Uni, 30V, 0,09A	31a	Njr	BA147/50, BA167..190, 1N5606..09,++
1S1691(A)	Si-Di	Gl, Uni, 36V, 0,1A	31a	Njr	BA147/50, BA167..190, 1N5606..09,++
1S1692(A)	Si-Di	Gl, Uni, 70V, 0,075A	31a	Njr	BA147/100, BA168..190, 1N5606..09,++
1S1693(A)	Si-Di	Gl, Uni, 70V, 0,1A	31a	Njr	BA147/100, BA168..190, 1N5606..09,++
1S1694(A)	Si-Di	Gl, Uni, 130V, 0,1A	31a	Njr	BA147/150, BA169..190, 1N5606..07,++
1S1695(A)	Si-Di	Gl, Uni, 200V, 0,04A	31a	Njr	BA147/230, BA190, BAY21, BAY68..90++
1S1696(A)	Si-Di	Gl, Uni, 225V, 0,1A	31a	Njr	BA147/230, BAY21, BAY66..90,++
1S1697(A)	Si-Di	Gl, Uni, 300V, 0,1A	31a	Njr	BA147/300, BAY21, BAY66..90,++
1S1696(A)	Si-Di	Gl, Uni, 380V, 0,1A	31a	Njr	BA158..159, BA199/450, BAY69..90,++
1S1699	Si-Di	Gl, S, 30V, 0,02A, <250ns	31a	Njr	BA157..159, BAV17..21, BAW48..50,++
1S17	Ge-Di	Uni, 115V, 50mA	31a	Ma1	AA117..116, AA132..133
1S170	Si-Di	Gl-L, 50V, 20A(Tc=120°)	32a	Nec	1N4525..30
1S1700	Si-Di	=1S1699: 40V, 0,12A	31a	Njr	BA157..159, BAV17..21, BAW48..50,++
1S1701	Si-Di	=1S1699: 80V, 0,1A	31a	Njr	BA157..159, BAV16..21, BAW49..50,++
1S1702	Si-Di	=1S1699: 65V, 0,12A	31a	Njr	BA157..159, BAV19..21, BAW49..50,++
1S1703	Si-Di	=1S1699: 100V, 0,02A	31a	Njr	BA157..159, BAV19..21, BAW49..50,++
1S1704(A)	Si-Di	=1S1699: 100V, 0,04A	31a	Njr	BA157..159, BAV19..21, BAW49..50,++
1S1705(A)	Si-Di	=1S1699: 120V, 0,2A	31a	Njr	BA157..159, BAV19..21, BAW50,++
1S1706	Si-Di	=1S1699: 200V, 0,02A	31a	Njr	BA157..159, BAV20..21, BAW50,++
1S1707(A)	Si-Di	=1S1699: 200V, 0,04A	31a	Njr	BA157..159, BAV20..21, BAW50,++
1S1708	Si-Di	=1S1699: 200V, 0,1A	31e	Njr	BA157..159, BAV20..21, BAW50,++
1S1709	Si-Di	=1S1699: 220V, 0,1A	31e	Njr	BA157..1+F762459, BA199, BAV21,++
1S171	Si-Di	=1S170: 100V	32a		1N4525..30
1S1710	Si-Di	SS, 30V, 0,05A, <4ns	31a	Njr	BA216, BAX13, BAX91, 1N4148..49,++
1S1711	Si-Di	SS, 40V, 0,05A, <4ns	31a	Njr	BA216, BAX13, BAX91, 1N4146..49,++
1S1712(A)	Si-Di	SS, 100V, 0,075A, <4ns	31a	Njr	BA219, BAX96, 1N4146..49, 1N4151,++
1S1713	Si-Di	SS, 50V, 0,075A, <2ns	31a	Njr	BAW62, BAX95, 1N4146..49, 1N4151,++
1S1714	Si-Di	SS, 75V, 0,075A, <2ns	31a	Njr	BAW62, BAX95, 1N4148..49, 1N4151,++
1S1715	Z-Di	6..7,1V, 0,3W	7c	Tos	BZX55/.., BZX79/.., ZPD.., 1N5234..40,++
1S1716	Z-Di	=1S1715: 6,9..8,1V	7c		—
1S1717	Z-Di	=1S1715: 7,9..9,1V	7c		—
1S1716	Z-Di	=1S1715: 8,9..10,1V	7c		—

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1S1719	Diac	Ub=28..42V, Ib<0,2mA, Itsm=2A	31f	Tos	1N5762, N413N, D3202U
1S172	Si-Di	=1S170: 200V	32a		1N4525..30
1S1720(R)	Si-Di	Gl-L, 250V, 10A(Tc=120°)		Tos	(BY239/400, BYX72/300)
1S1721	Si-Di	UHF, S-Band-M	Koax	Tos	—
1S1722	Si-Di	UHF, S-Band-M	31a	Tos	—
1S1723	Si-Di	Gl, Uni, 100V, 1,3A	34a		BY251..255, BY226..227, 2N5392..99,++
1S1723R...1733R	Si-Di	=1S1723..1733:	34b		→1S1723..1733
1S1724	Si-Di	=1S1723: 150V	34a		BY251..255, BY226..227, 2N5393..99,++
1S1725	Si-Di	=1S1723: 200V	34a		BY251..255, BY226..227, 2N5393..99,++
1S1726	Si-Di	=1S1723: 250V	34a		BY252..255, BY226..227, 2N5394..99,++
1S1727	Si-Di	=1S1723: 300V	34a		BY252..255, BY226..227, 2N5394..99,++
1S1726	Si-Di	=1S1723: 400V	34a		BY252..255, BY226..227, 2N5395..99,++
1S1729	Si-Di	=1S1723: 500V	34a		BY253..255, BY226..227, 2N5396..99,++
1S173	Si-Di	=1S170: 300V	32a		1N4526..30
1S1730	Si-Di	=1S1723: 600V	34a		BY253..255, BY226..227, 2N5397..99,++
1S1731	Si-Di	=1S1723: 600V	34a		BY254..255, BY227, 2N5396..99,++
1S1732	Si-Di	=1S1723: 1000V	34a		BY255, BY227, BYX66..67, 2N5399,++
1S1733	Si-Di	=1S1723: 1200V	34a		BY255, BY227, BYW17/1200, BYX67,++
1S1734	Z-Di	4,5..5,5V, 1W	34		BZW22/.., BZX61/.., ZPY.., 1N5917..53,++
1S1735	Z-Di	=1S1734: 5..6,5V	34		—
1S1736	Z-Di	=1S1734: 6..8V	34		—
1S1737	Z-Di	=1S1734: 7..10V	34		—
1S1736	Z-Di	=1S1734: 9..12V	34		—
1S1739	Z-Di	=1S1734: 11..14V	34		—
1S174	Si-Di	=1S170: 400V	32a		1N4526..30
1S1740	Z-Di	=1S1734: 13..16V	34		—
1S1741	Z-Di	=1S1734: 15..19V	34		—
1S1742	Z-Di	=1S1734: 18..22V	34		—
1S1743	Z-Di	=1S1734: 20..27V	34		—
1S1744	Z-Di	=1S1734: 25..35V	34		—
1S1745	Z-Di	=1S1734: 30..40V	34		—
1S1746	Z-Di	=1S1734: 35..50V	34		—
1S1747	Z-Di	=1S1734: 45..60V	34		—
1S1748	Z-Di	=1S1734: 55..70V	34		—
1S1749	Z-Di	=1S1734: 65..80V	34		—
1S175	Si-Di	=1S170: 500V	32a		1N4527..30
1S1750	Z-Di	=1S1734: 75..90V	34		—
1S1751	Z-Di	=1S1734: 85..100V	34		—
1S1752	Z-Di	=1S1734: 95..110V	34		—
1S1753	Z-Di	=1S1734: 100..120V	34		—
1S1754	Z-Di	=1S1734: 110..130V	34		—
1S1755	Z-Di	=1S1734: 120..140V	34		—
1S1756	Z-Di	=1S1734: 130..150V	34		—
1S1757	Si-Di	Modulator	31a	Tos	—
1S1758	Si-Di	Modulator	31a	Tos	—
1S1759	Si-Di	Modulator	31a	Tos	—
1S176	Si-Di	=1S170: 600V	32a		1N4527..30
1S1760	Ge-Di	Tunnel-Di	34	Nec	—
1S1761	Ge-Di	Tunnel-Di	34	Nec	—
1S1762	Ge-Di	Tunnel-Di	34	Nec	—
1S1763	Ge-Di	Tunnel-Di	34	Nec	—
1S1764	Ge-Di	Tunnel-Di	34	Nec	—
1S1765	C-Di	FM/VHF-AFC	31a	Nec	BA111, BA124, 1S2790, 1SV50,++
1S1766	Z-Di	4,5..5,5V, 0,25W	31a		BZX55/.., BZX79/.., ZPY..F7676, 1N5230..59,++
1S1767	Z-Di	=1S1766: 5..6,5V	31a		—
1S1766	Z-Di	=1S1766: 6..8V	31a		—
1S1769	Z-Di	=1S1766: 7..10V	31f		—
1S177	Si-Di	Gl-L, 100V, 15A(Tc=120°)	32a	Nec	1N4525..30
1S1770	Z-Di	=1S1766: 9..12V	31a		—
1S1771	Z-Di	=1S1766: 11..14V	31a		—
1S1772	Z-Di	=1S1766: 13..16V	31a		—
1S1773	Z-Di	=1S1766: 15..19V	31a		—
1S1774	Z-Di	=1S1766: 18..22V	31a		—
1S1775	Z-Di	=1S1766: 20..27V	31a		—
1S1776	Z-Di	=1S1766: 25..35V	31a		—
1S1777	Z-Di	=1S1766: 30..40V	31a		—

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1S1778	Ref-Di	8..9V	34		BZX51, 1N4780
1S1779	Ref-Di	8..9V	34		BZX52, 1N4781
1S178	Si-Di	=1S177: 200V	32a		1N4525..30
1S1780	Ref-Di	8..9V	34		BZX53, 1N4782
1S1781	Ref-Di	8..9,5V	31a	Stl	BZX51, 1N4780
1S1782	Ref-Di	8..9,5V	31a		BZX52, 1N4781
1S1783	Ref-Di	8..9,5V	31a		BZX53+F7787, 1N4782
1S1784	Z-Di	62V, 1W	34	Stl	BZW22/.., BZX61/.., ZPY.., 1N5944..56,++
1S1785	Z-Di	=1S1784: 68V	34		—
1S1786	Z-Di	=1S1784: 82V	34		—
1S1787	Z-Di	=1S1784: 100V	34		—
1S1786	Z-Di	=1S1784: 120V	34		—
1S1789	Z-Di	=1S1784: 130V	34		—
1S179	Si-Di	=1S177: 300V	32a		1N4526..30
1S1790	Z-Di	=1S1784: 150V	34		—
1S1791	Z-Di	=1S1784: 180V	34		—
1S1792	Z-Di	=1S1784: 200V	34		—
1S1793	Z-Di	=1S1784: 220V	34		—
1S1794	Z-Di	=1S1784: 250V	34		—
1S1795	Z-Di	=1S1794: 300V	34		—
1S1796	Si-Di	SS, 30V, 0,1A, <4ns	31a	Hit	BA317, BAY38, BAY71, 1N4148..49,++
1S1798	Si-Di	GI-L, 100V, 8A(Tc=135°)	32a	Org	BYX42/300, BYX98/300
1S1798R...1804R	Si-Di	=1S1798..1804:	32b		BYX42/..R, BYX98/..R
1S1799	Si-Di	=1S1798: 200V	32a		BYX42/300, BYX98/300
1S18	Ge-Di	Uni, 115V, 50mA	31a	Mat	AA117..118, AA132..133
1S180	Si-Di	Dem, Uni, 70V, 0,1A	31a	Tos	BA147/100, BA186..190, BAY19..21,++
1S1800	Si-Di	=1S1798: 300V	32a		BYX42/300, BYX98/300
1S1801	Si-Di	=1S1798: 400V	32a		BYX42/600, BYX98/600
1S1802	Si-Di	=1S1798: 600V	32a		BYX42/600, BYX98/600
1S1803	Si-Di	=1S1798: 600V	32a		BYX42/900, BYX98/900
1S1804	Si-Di	=1S1798: 1000V	32a		BYX42/1000, BYX98/1000
1S1905(A)	C-Di	FM/VHF-AFC/Tuning	10	Njr	BB109, BB143, MV109, 1SV50,++
1S1806(A)	C-Di	FM/VHF-AFC/Tuning	10	Njr	BB109, BB143, MV109, 1SV50,++
1S1807	Si-Di	UHF-M, 890MHz	31a	Tos	—
1S1808	Si-Di	GI-L, 600V, 210A(Tc=105°)	73b	Rhm	1N3740R..44R
1S1809	Si-Di	=1S1806: 800V	73b		1N3741R..44R
1S181	Si-Di	=1S180: 120V	31a		BA147/150, BA189..190, BAY20..21,++
1S1810	Si-Di	=1S1808: 1000V	73b		1N3742R..44R
1S1811	Si-Di	=1S1808: 1200V	73b		1N3743R..44R
1S1812	Si-Di	=1S1808: 1400V	73b		1N3744R
1S1813	Si-Di	=1S1808: 1800V	73b		—
1S1814	Si-Di	GI-L, 600V, 300A(Tc=105°)	73b	Rhm	—
1S1815	Si-Di	=1S1814: 600V	73b		—
1S1818	Si-Di	=1S1814: 1000V	73b		—
1S1817	Si-Di	=1S1814: 1200V	73b		—
1S1818	Si-Di	=1S1814: 1400V	73b		—
1S1819	Si-Di	=1S1814: 1600V	73b		—
1S182	Si-Di	=1S190: 220V	31a		BA147/230, BAY21, BAY46, BAY86,++
1S1820	Si-Di	UHF-M, 887MHz	31a	Hit	—
1S1821	Si-Di	GI, contr.av., 600V, 1A	34a	Nec,Shi	BYW55..56, 1N4248..49, 1N5082,++
1S1821R..1824R	Si-Di	=1S1821..1824:	34b		→1S1821..1824
1S1822	Si-Di		34a		—
1S1823	Si-Di		34a		—
1S1824	Si-Di		34a		—
1S1825	Si-Di	GI, contr.av., 800V, 12A(Tc=180°)	32a	Nec	1N4528..30
1S1829	Si-Di	GI, Uni, 600V, 1A	31a	Tos	BY127, BY133, BY227, 1N4006..07,++
1S183	Si-Di	=1S180: 320V	31a		BA147/300, BAY21, BAY46, BAY88,++
1S1830	Si-Di	=1S1829: 1000V	31a		BY127, BY133, BY227, 1N4007,++
1S1831	Si-Di	GI, 2000V, 0,15A	31a	Tos	BAY91, BY203/20, SHG2
1S1832	Si-Di	GI, S, 1800V, 0,7A	31a	Tos	DM516
1S1834	Si-Di	GI, S, 400V, 1A, <350ns	31a	Tos	BY201/4, BYX55/600, MR814, RGP10G,++
1S1835	Si-Di	=1S1834: 600V	31a		BY201/6, BYX55/600, MR816, RGP10J,++
1S1836	Si-Di	TV-kV-GI, 18kV, 2mA	31a	Tos	BY476, BY711
1S1837	Si-Di	=1S1838: 25kV	31a		BY478, BY713
1S1836	Si-Di	=1S1838: 45kV	31a		—
1S184	Si-Di	Dem, S, 15V, 0,04A	31a	Tos	BA281

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1S1841	Si-Di	GI-L, 400V, 25A(Tc=110°)	32	Tos	1N3765..68, 1N4526..30
1S1842	Si-Di	=1S1841: 600V	32		1N3765..88, 1N4527..30
1S1843	Si-Di	=1S1841: 600V	32		1N3768..68, 1N4528..30
1S1844	Si-Di	=1S1841: 1000V	32		1N3768, 1N4529..30
1S1845	Si-Di	GI, 200V, 0,5A	31a		BY251..255, BY228..227, BYW17/200,++
1S1845A	Si-Di	=1S1845: 400V	31a		BY252..255, BY228..227, BYW17/400,++
1S1845B	Si-Di	=1S1845: 600V	31a		BY253..255, BY228..227, BYW17/600,++
1S1845C	Si-Di	=1S1845: 600V	31a		BY254..255, BY227, BYW17/600,++
1S1845D	Si-Di	=1S1845: 1000V	31a		BY255, BY227, BYW17/1000, BYX86,++
1S1845E	Si-Di	=1S1845: 1200V	31a		BY255, BY227, BYW17/1200, BYX87,++
1S1846(A..E)	Si-Di	=1S1845(A..E): 1A	31a		→1S1845(A E)
1S1847(A..E)	Si-Di	GI-L, 200..1200V, 8A(Tc=50°)	73a		BYX42/.., BYX98/..
1S1848(A..E)	Si-Di	GI-L, 200..1200V, 22A(Tc=50°)	73a		BYX..96/..
1S1849(R)	Si-Di	Dual, GI, 100V, 1,5A	12e/h	Sak	(2xBY226..227, 2xBY251..255,++)
1S165	Si-Di	Dem, S, 15V, 0,04A	31a	Tos	BA261
1S1650(R)	Si-Di	=1S1849: 200V	12e/h		(2xBY228..227, 2xBY251..255,++)
1S1651(R)	Si-Di	=1S1849: 400V	12e/h		(2xBY226..227, 2xBY252..255,++)
1S1655	Si-Di	Snap-off-Di, SS	31a	Nec	—
1S1856	Si-Di	Snap-off-Di, SS	Koax	Nec	—
1S1857	Si-Di	Snap-off-Di, SS	Koax	Nec	—
1S1858	Si-Di	Schottky-Di, SS, 10V, 0,03A, <1ns	Koax	Nec	BAT19, 1SS68, 1SS106
1S168	Ge-Di	Uni, 75V, 30mA	31a	Say	AA117..118, AA132..133
1S1860	Si-Di	Schottky-Di, UHF-M, 855MHz, 3V, 30mA	31a	Nec	BA480..481, BAR19, BAT29
1S1861	Si-Di	GI-L, 1000V, 40A(Tc=104°)	32	Inr	BYX56/1000, BYX97/1200
1S1682	Si-Di	GI-L, 1000V, 60A(Tc=126°)	32	Inr	DS75-11B
1S1863	Si-Di	GI-L, 100V, 150A(Tc=118°)	73a	Inr	1N4587..96
1S1864	Si-Di	=1S1683: 150V	73a		1N4588..96
1S1865	Si-Di	=1S1683: 200V	73a		1N4588..96
1S1866	Si-Di	=1S1683: 300V	73a		1N4589..96
1S1687	Si-Di	=1S1963: 400V	73a		1N4590..96
1S1688	Si-Di	=1S1963: 500V	73a		1N4591..96
1S1869	Si-Di	=1S1863: 600V	73a		1N4592..96
1S187(3)	Ge-Di	Dem, 40V, 50mA	31a	Say	AA113, AA119, 1N34, 1N54, 1N80
1S1870	Si-Di	=1S1683: 600V	73a		1N4593..96
1S1871	Si-Di	=1S1963: 1000V	73a		1N4594..96
1S1872	Si-Di	GI-L, 100V, 250A(Tc=107°)	73a	Inr	1N3735..44
1S1873	Si-Di	=1S1872: 150V	73a		1N3736..44
1S1874	Si-Di	=1S1872: 200V	73a		1N3736..44
1S1875	Si-Di	=1S1872: 300V	73a		1N3737..44
1S1876	Si-Di	=1S1872: 400V	73a		1N3736..44
1S1877	Si-Di	=1S1872: 500V	73a		1N3739..44
1S1878	Si-Di	=1S1872: 600V	73a		1N3740..44
1S1879	Si-Di	=1S1872: 800V	73a		1N3741..44
1S168(AM,FM,G)	Ge-Di	Dem, 25..40V, 50mA	31a	Say	AA113, AA119, 1N34, 1N54, 1N60,++
1S1880	Si-Di	=1S1872: 1000V	73a		1N3742..44
1S1681	Si-Di	=1S1872: 1200V	73a		1N3743..44
1S1882	Si-Di	=1S1872: 1400V	73a		1N3744
1S1685(A)	Si-Di	GI, 100V, 1A, A=1,2A	31a	Tos	BY126..127, BY133..135, 1N4002..07,++
1S1686(A)	Si-Di	=1S1685: 200V	31a		BY126..127, BY133..134, 1N4003..07,++
1S1887(A)	Si-Di	=1S1685: 400V	31a		BY126..127, BY133..134, 1N4004..07,++
1S1688(A)	Si-Di	=1S1865: 600V	31a		BY126..127, BY133..134, 1N4005..07,++
1S189	Ge-Di	Dem, 50V, 40mA	31a	Say	AA113, AA119, 1N34, 1N54, 1N60
1S1890	Si-Di	GI, Uni, 600V, 1,2A	34a	Tos	BY226..227, BY253..255, 1N5397..99,++
1S1891	Si-Di	=1S1890: 600V	34a		BY227, BY254..255, 1N5398..99,++
1S1892	Si-Di	=1S1890: 1000V	34a		BY227, BY255, BYX86, 1N5398..99,++
1S1893	C-Di	AFC	31a	Sak	BA124..125, BB119, 1S2790, 1SV50,++
1S1894(A...D)	C-Di	VHF-AFC, VHF-Tuning	31a	Sak	BB105G, BB205G, BB305G, BB505G,++
1S1895(A...D)	C-Di	VHF-AFC, VHF-Tuning	31a	Sak	BB105G, BB205G, BB305G, BB505G,++
1S1897	Si-Di	TV-Demper-Di, 500V, 1,5A, <600ns	34	Sak	BY258/500, BY298, BYV14, RGP15J,++
1S1898	Si-Di	=1S1897: 800V	34		BY256/800, BY299, BYV15, RGP15K,++
1S1899	Si-Di	=1S1897: 1000V	34		BY246/1000, BY299, BYV16, RGP15M,++
1S19	Ge-Di	Dem, 15V, 35mA	31a	Mat	AA112..114, 1N34, 1N54, 1N60,++
1S190	Z-Di	4,4..5,6V, 0,4W	31a	Njr	BZX55/.., BZX79/.., ZPD.., 1N5231..50,++
1S1901	Si-Di	TV-Damper-Di, 1500V, 1,5A, <1,5µs	22	Sak	BY359/1500
1S1902	Si-Di	GI, S, 500V, 0,8A, <300ns	34	Sak	BY201/5, BYX55/600, RGP10J, 1N4946,++
1S1903	Si-Br	GI-Br, 70V(eff), 1,5A		Sak	B80C1500, etc.

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1S1904	Si-Br	=1S1903: 140V			B140C1500, etc.
1S1905	Si-Di	Dual, 100V, 1A	12j	Sak	2x(BY126..127, BY133..135, 1N4002,++)
1S1905R...1907R	Si-Di	=1S1905..1907	12h		→1S1905..1907
1S1906	Si-Di	=1S1905: 200V	12j		2x(BY126..127, BY133..134, 1N4003,++)
1S1907	Si-Di	=1S1905: 400V	12j		2x(BY126..127, BY133..134, 1N4004,++)
1S1906	Si-Di	Gl, S, 100V, 1,5A, <300ns		Sak	(BY205/100, BYV67/300, ESM161/300R,+
1S1909	Si-Di	=1S1908: 200V			(BY205/200, BYV87/300, ESM181/300R,+
1S191	Z-Di	=1S190: 5,4..6,6V	31a		—
1S1910	Si-Di	Gl, S, 1300V, 1A, <1µs	34b	Sak	BY228, BY231/1400, BY400, BY448
1S1911	Si-Di	=1S1910: 1500V	34b		BY226, BY231/1500, BY400, BY448
1S1912	Si-Di	kV-Gl, 10kV, 3mA, <300ns	31a	Sak	BY509..510, BY707..709
1S1914	Si-Di	Gl, Uni, 100V, 1,5A	34a	Sak	BY226..127, BY251..255, 1N5392..99,++
1S1915	Si-Di	=1S1914: 200V	34a		BY226..127, BY251..255, 1N5393..99,++
1S1916	Si-Di	=1S1914: 400V	34a		BY226..127, BY252..255, 1N5395..99,++
1S1917	Si-Di	=1S1914: 800V	34a		BY226..127, BY253..255, 1N5397..99,++
1S1916	Si-Di	=1S1914: 800V	34a		BY227, BY254..255, 1N5398..99,++
1S1919	Si-Di	=1S1914: 1000V	34a		BY227, BY255, BYX87, 1N5399,++
1S192	Z-Di	=1S190: 6,4..7,6V	31a		—
1S1920	Si-Di	Gl, Uni, 1200V, 0,8A	34	Hit	BY133, BY227, BYX95, GP10Q, EM513
1S1921A	Si-Di	Gl, Uni, 200V, 0,1A	31a	Hit	BA157..159, BA147/230, BAY88..91,++
1S1921B	Si-Di	=1S1921A: 400V	31a		BA157..159, BAY88..91, BY203/12,++
1S1921C	Si-Di	=1S1921A: 600V	31a		BA158..159, BAY89..91, BY203/12,++
1S1921D	Si-Di	=1S1921A: 800V	31a		BA159, BAY9091, BY203/12,++
1S1921E	Si-Di	=1S1921A: 1000V	31a		BA159, BAY9091, BY203/12,++
1S1921F	Si-Di	=1S1921A: 1200V	31a		BAY91, BY203/12, BY58+F78714, RGP01-12,++
1S1922	C-Di	AFC	31a	Njr	BA124..125, BB119, 1SV114, 1S125,++
1S1923	C-Di	AFC	31a	Njr	BA124..125, BB119, 1SV114, 1S125,++
1S1924	C-Di	AFC	31a	Njr	BA124..125, BB119, 1SV114, 1S125,++
1S1925	Si-Di	Schottky-Di, UHF-M, 5V, 50mA, 890MHz	31a	Njr	—
1S1926	Si-Di	Schottky-Di, UHF-M, 5V, 25mA, 890MHz	31a	Njr	BA480..481, BAR19, BAT29
1S1927	Si-Di	Gl-L, contr.av., 2000V, 7A(Tc=120°)	32b	Fjd	—
1S1926	Si-Di	Gl-L, contr.av., 2000V, 12A(Tc=120°)	32b	Fjd	—
1S1929	Si-Di	Gl-L, contr.av., 3000V, 12A(Tc=120°)	32b	Fjd	—
1S193	Z-Di	=1S190: 7,4..8,6V	31a		—
1S1930	Si-Di	Gl-L, contr.av., 2000V, 24A(Tc=120°)	32b	Fjd	—
1S1931	Si-Di	Gl-L, contr.av., 3000V, 24A(Tc=120°)	32b	Fjd	—
1S1932	Si-Di	Gl-L, contr.av., 2000V, 50A(Tc=120°)	73b	Fjd	—
1S1933	Si-Di	=1S1932: 3000V	73b	Fjd	—
1S1934	Si-Di	Gl-L, 100V, 20A(130°)	32a	Org	1N3765..3788, 1N4525..4530
1S1934R..1939R	Si-Di	=1S1934..1939:	32b		D24/..C, 1N3765R..3768R
1S1935	Si-Di	=1S1934: 200V	32a		1N3765..3768, 1N4525..4530
1S1936	Si-Di	=1S1934: 400V	32a		1N3765..3788, 1N4526..4530
1S1937	Si-Di	=1S1934: 800V	32a		1N3765..3768, 1N4527..4530
1S1938	Si-Di	=1S1934: 800V	32a		1N3766..3768, 1N4526..4530
1S1939	Si-Di	=1S1934: 1000V	32a		1N3788, 1N4529..4530
1S194	Z-Di	=1S190: 8,4..9,6V	31a		—
1S1941	Si-Di	Gl, Uni, 100V, 0,5A	31a	Tos	BY133..135, BY226..227, 1N4002..07,++
1S1942	Si-Di	=1S1941: 200V	31a		BY133..134, BY226..227, 1N4003..07,++
1S1943	Si-Di	=1S1941: 400V	31a		BY133..134, BY226..227, 1N4004..07,++
1S1944	Si-Di	=1S1941: 800V	31a		BY133..134, BY226..227, 1N4005..07,++
1S1948	Si-Di	Gl, Uni, 200V, 1,3A	31a	Hit	BY226..227, BY251..255, 1N5393..99,++
1S1949	Si-Di	=1S1948: 400V	31a		BY226..227, BY252..255, 1N5395..99,++
1S195	Z-Di	=1S190: 9,4..10,6V	31a		—
1S1950	Si-Di	=1S1948: 800V	31a		BY226..227, BY253..255, 1N5397..99,++
1S1951	Z-Di	31..35V, 1W	31a	Hit	BZW22/C33, BZX61/C33, ZPY33, 1N5937,++
1S1952	Z-Di	1,8..2,6V, 1W	31a	Hit	BZW22/.., BZX61/.., ZPY.., 1N5913..36,++
1S1953	Z-Di	=1S1952: 2,5..3,5V	31a		—
1S1954	Z-Di	=1S1952: 3,4..4,6V	31a		—
1S1955	Z-Di	=1S1952: 4,4..5,6V	31a		—
1S1956	Z-Di	=1S1952: 5,2..6,6V	31a		—
1S1957	Z-Di	=1S1952: 6,4..7,9V	31a		—
1S1956	Z-Di	=1S1952: 7,7..8,8V	31a		—
1S1959	Z-Di	=1S1952: 8,5..9,6V	31a		—
1S196	Z-Di	=1S190: 10,4..11,6V	31a		—
1S1960	Z-Di	=1S1952: 9,4..10,6V	31a		—
1S1961	Z-Di	=1S1952: 10,4..11,6V	31a		—

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1S1962	Z-Di	=1S1952: 11,4..12,7V	31a		—
1S1963	Z-Di	=1S1952: 12,4..14,1V	31a		—
1S1964	Z-Di	=1S1952: 13,8..15,6V	31a		—
1S1965	Z-Di	=1S1952: 15,3..17,1V	31a		—
1S1966	Z-Di	=1S1952: 16,8..19,1V	31a		—
1S1967	Z-Di	=1S1952: 18,8..21,2V	31a		—
1S1966	Z-Di	=1S1952: 20,8..23,3V	31a		—
1S1969	Z-Di	=1S1952: 22,7..25,6V	31a		—
1S197	Z-Di	=1S190: 11,4..12,6V	31a		—
1S1970	Z-Di	=1S1952: 25,1..28,9V	31a		—
1S1971	Z-Di	=1S1952: 28..32V	31a		—
1S1972(M)	Si-Di	SS, 75V, 0,2A, <4ns	31a	Nec, Tos	BAW62, BAX95, 1N4148..49, 1N4446..49++
1S1973(M)	Si-Di	SS, 35V, 0,1A, <4ns	31a	Nec, Tos	BA318, BAY38, BAX90, 1N4148..49, ++
1S196	Z-Di	=1S190: 12,4..16,1V	31a		—
1S199	Z-Di	=1S190: 15,9..20V	31a		—
1S1991	Diac	Ub=23..37V, Ib<0,2mA, Itsm=2A	31l	Sak	1N5761, N413M, D3202Y, BR100, DO201YR
1S1992	Si-Di	Schottky-Di, 30V, 0,02A	31a	Nac	BAT81, HSS100..102
1S1993	Si-Di	Schottky-Di, 20V, 0,03A	31a	Nec	BAT81, HSS100..102
1S1994	Si-Di	Schottky-Di, 30V, 0,03A	31a	Nec	BAT81, HSS100..102
1S1995	Si-Di	Schottky-Di, 20V, 0,05A	31a	Nec	BAT81, HSS100..102
1S1996	Si-Di	Gl, Uni, 200V, 3A(Tc=128°)	≈34a	Hit	BY251..255, 1N5402..08, (BY205/200,++)
1S1996R...1999R	Si-Di	=1S1996 .C79231999	≈34b		BY251..255, 1N5402..08, (BY205/..,++)
1S1997	Si-Di	=1S1996: 400V	≈34a		BY252..255, 1N5404..08, (BY205/400,++)
1S1996	Si-Di	=1S1996: 600V	≈34a		BY253..255, 1N5406..08, (BY205/600,++)
1S1999	Si-Di	=1S1996: 600V	≈34a		BY254..255, 1N5407..08, (BY205/800,++)
1S20	Ge-Di	S, 30V, <500ns	31a	Tos	AAY27..28, 1N276
1S200	Ge-Di	Dem, 35V, 25mA	31a	Njr	AA112..114, AA119, 1N34, 1N54, 1N60,++
1S2000	Si-Di	Gl-L, 400V, 10A(Tc=128°)	32a	Hit	1N3765..3768, 1N4526..4530
1S2000R..2002R	Si-Di	=1S2000..2002:	32b		D24/..C, 1N3765R..3768R
1S2001	Si-Di	=1S2000: 600V	32a		1N3765..3768, 1N4527..4530
1S2002	Si-Di	=1S2000: 800V	32a		1N3766..3768, 1N4528..4530
1S2003	Si-Di	Gl-L, 100V, 10A(Tc=125°)	75a	Hit	1N3492..3495
1S2003R	Si-Di	=1S2003.	75b		DS25-..A, 1N3492R..3495R
1S2004(R)	Si-Di	Gl-L, 100V, 15A(Tc=110°)		Hit	(BY205/100, BY249/300, BYV87/300,++)
1S2005	Si-Di	Gl-L, 400V, 20A(Tc=100°)	32a	Hit	1N3765..3768, 1N4526..4530
1S2005R..2007R	Si-Di	=1S2005..2007:	32b		D24/..C, 1N3765R..3768R
1S2006	Si-Di	=1S2005: 600V	32a		1N3765..3768, 1N4527..4530
1S2007	Si-Di	=1S2005: 800V	32a		1N3768..3768, 1N4528..4530
1S2008(R)	Si-Di	Gl-L, 100V, 75A(Tc=120°)		Hit	—
1S2009(R)	Si-Di	=1S2008: 200V			—
1S201	Ge-Di	20V	31	Njr	—
1S2010(R)	Si-Di	=1S2008: 300V			—
1S2011	Si-Di	Gl-L, 1000V, 20A(Tc=100°)	32a	Hit	1N3768, 1N4529..4530
1S2011R	Si-Di	=1S2011:	32b		D24/1200C, 1N3768R
1S2012	Si-Di	Gl-L, 200V, 100A(Tc=104°)	73a	Hit	1N3289..3297, 1N4588..4596
1S2013	Si-Di	=1S2012: 400V	73a		1N3291..3297, 1N4590..4596
1S2014	Si-Di	=1S2012: 600V	73a		1N3293..3297, 1N4592..4596
1S2015	Si-Di	=1S2012: 800V	73a		1N3294..3297, 1N4593..4596
1S2016	Si-Di	=1S2012: 1000V	73a		1N3295..3297, 1N4594..4596
1S2017	Si-Di	=1S2012: 1300V	73a		1N3297, 1N4596
1S2018	Si-Di	=1S2012: 1500V	73a		—
1S2019	Si-Di	Gl-L, 200V, 100A(Tc=90°)	73a	Hit	1N3289..3297, 1N4588..4596
1S202	Ge-Di	20V	31	Njr	—
1S2020	Si-Di	=1S2019: 400V	73a		1N3291..3297, 1N4590..4596
1S2021	Si-Di	=1S2019: 600V	73a		1N3293..3297, 1N4592..4596
1S2022	Si-Di	=1S2019: 800V	73a		1N3294..3297, 1N4593..4596
1S2023	Si-Di	=1S2019: 1000V	73a		1N3295..3297, 1N4594..4596
1S2024	Si-Di	=1S2019: 1300V	73a		1N3297, 1N4596
1S2025	Si-Di	=1S2019: 1500V	73a		—
1S2026(R)	Si-Di	Gl-L, 100V, 150A(Tc=110°)		Hit	—
1S2027(R)	Si-Di	=1S2026: 200V			—
1S2028(R)	Si-Di	=1S2026: 300V			—
1S2029	Si-Di	Gl-L, 600V, 30A(Tc=95°)	32a	Hit	1N3768..3768, 1N4528..4530
1S2029R	Si-Di	=1S2029:	32b		D34/..C, 1N3766R..3768R
1S203	Ge-Di	20V	31	Njr	—
1S2030(A)[Texas]	Z-Di	3V, 0,4W, 10%, (A=5%)	31a	Tix	BZX55/.., BZX83/.., ZPD.., 1N5225..57

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1S2030(R)	Si-Di	Gl-L, 100V, 250A(Tc=120°)		Hit	—
1S2031(R)	Si-Di	=1S2030: 200V			—
1S2032(R)	Si-Di	=1S2030: 300V			—
1S2033	Si-Di	Gl-L, 800V, 50A(Tc=60°)	73a	Hit	1N3294..3297
1S2033(A)[Texas]	Z-Di	=1S2030[Texas]: 3,3V	31a	Tix	→1S2030
1S2033R	Si-Di	=1S2033:	73a		1N3294R..3297R
1S2034	Si-Di	Gl-L, 200V, 20A(Tc=115°)	75a	Hit	1N3493..3295
1S2034R..2035R	Si-Di	=1S2034:	75b		DS25-..A, 1N3493R..3295R
1S2035	Si-Di	=1S2034: 300V	75a		1N3494..3295
1S2036	Si-Di	Gl-L, 200V, 10A(Tc=125°)	75a	Hit	1N3493..3295
1S2036(A)[Texas]	Z-Di	=1S2030[Texas]: 3,6V	31a	Tix	→1S2030
1S2036R...2037R	Si-Di	=1S2036:	75b		DS25-.., 1N3493R..3295R
1S2037	Si-Di	=1S2036: 300V	75a		1N3494..3295
1S2036	Si-Di	Gl-L, 2500V, 300A(Tc=90°)	73b	Hit	—
1S2039	Si-Di	=1S2036: 3000V	73b		—
1S2039(A)[Texas]	Z-Di	=1S2030[Texas]: 3,9V	31a	Tix	→1S2030
1S204	Si-Di	Gl, Uni, 250V, 0,1A	31a	Njr	BA157..159, BA199/250, BAY88..90, ++
1S2040	Si-Di	=1S2038: 4000V	73b		—
1S2041	Si-Di	Gl-L, 2000V, 600A(Tc=100°)		Hit	—
1S2042	Si-Di	=1S2041: 2500V			—
1S2043(A)[Texas]	Z-Di	=1S2030[Texas]: 4,3V	31a	Tix	→1S2030
1S2043[Hitachi]	Z-Di	1,8..2,6V, 10W(Tc=115°)	32b	Hit	BZX98/.., BZY93/.., ZX.., 1N2970..90
1S2044[Hitachi]	Z-Di	=1S2043[Hitachi]: 2,5..3,5V	32b		—
1S2045[Hitachi]	Z-Di	=1S2043[Hitachi]: 3,4..4,6V	32b		—
1S2046[Hitachi]	Z-Di	=1S2043[Hitachi]: 4,4..5,4V	32b		—
1S2047(A)[Texas]	Z-Di	=1S2030[Texas]: 4,7V	31a	Tix	→1S2030
1S2047[Hitachi]	Z-Di	=1S2043[Hitachi]: 5,2..6,8V	32b	Hit	→1S2043
1S2048[Hitachi]	Z-Di	=1S2043[Hitachi]: 6,2..7,9V	32b		—
1S2049[Hitachi]	Z-Di	=1S2043[Hitachi]: 7,7..8,7V	32b		—
1S205	Si-Di	=1S204: 350V	31a		BA157..159, BA199/350, BAY88..90, ++
1S2050[Hitachi]	Z-Di	=1S2043[Hitachi]: 8,5..9,6V	32b		—
1S2051(A)[Texas]	Z-Di	=1S2030[Texas]: 5,1V	31a	Tix	→1S2030
1S2051[Hitachi]	Z-Di	=1S2043[Hitachi]: 9,4..10,6V	32b	Hit	→1S2043
1S2052[Hitachi]	Z-Di	=1S2043[Hitachi]: 10,4..11,6V	32b		—
1S2053[Hitachi]	Z-Di	=1S2043[Hitachi]: 11,4..12,7V	32b		—
1S2054[Hitachi]	Z-Di	=1S2043[Hitachi]: 12,4..14,1V	32b		—
1S2055[Hitachi]	Z-Di	=1S2043[Hitachi]: 13,5..15,6V	32b		—
1S2056(A)[Texas]	Z-Di	=1S2030[Texas]: 5,6V	31a	Tix	→1S2030
1S2056[Hitachi]	Z-Di	=1S2043[Hitachi]: 15,3..17,1V	32b	Hit	→1S2043
1S2057[Hitachi]	Z-Di	=1S2043[Hitachi]: 16,8..19,1V	32b		—
1S2056[Hitachi]	Z-Di	=1S2043[Hitachi]: 18,8..21,2V	32b		—
1S2059[Hitachi]	Z-Di	=1S2043[Hitachi]: 20,8..23,3V	32b		—
1S206	Si-Di	=1S204: 450V	31a		BA158..159, BA199/450, BAY89..90, ++
1S2060[Hitachi]	Z-Di	=1S2043[Hitachi]: 22,7..25,6V	32b		—
1S2061[Hitachi]	Z-Di	=1S2043[Hitachi]: 25,1..28,9V	32b		—
1S2062(A)[Texas]	Z-Di	=1S2030[Texas]: 6,2V	8a	Tix	→1S2030
1S2062[Hitachi]	Z-Di	=1S2043[Hitachi]: 28..32V	32b		—
1S2063	Si-Di	Gl, Uni, 800V, 1,3A	31a	Hit	BY227, BY254..2+F802555, 1N5398..99, ++
1S2064	Trigger-Di	Ub=28..36V, Ib<0,2mA, Itsm=2A	31l	Hit	—
1S2067[Njr]	Ref-Di	8,5V	31a	Njr	BZX51, 1N4760
1S2068(A)[Texas]	Z-Di	=1S2030[Texas]: 8,8V	31a	Tix	→1S2030
1S2068[Njr]	Ref-Di	8,5V	31a	Njr	BZX51, 1N4781
1S2069[Njr]	Ref-Di	8,5V	31a	Njr	BZX53, 1N4782
1S207	Si-Di	=1S204: 550V	31a		BA158..159, BA199/550, BAY89..90, ++
1S2070	Si-Di	SS, 50V, 45mA, <3ns	31a	Fui	BA318, BAY36, 1N4305, 1N4148..49, ++
1S2071	Si-Di	SS, 22V, 45mA, <5ns	31a	Fui	BA318, BAY36, 1N4305, 1N4148..49, ++
1S2072	Si-Di	SS, 80V, 0,2A, <6ns	31a	Fui	BAW82, BAX95, 1N4148..49, 1N4446..49++
1S2074H	Si-Di	SS, 50V, 0,15A, <4ns	31a	Hit	BAW82, BAX95, 1N4148..49, 1N4446..49++
1S2075(A)[Texas[	Z-Di	=1S2060[Texas]: 7,5V	31a	tix	→1S2030
1S2075K	Si-Di	SS, 35V, 0,1A, <6ns	31a	Hit	BA318, BAY36, 1N4305, 1N4148..49, ++
1S2076	Si-Di	Dem, SS, 35V, 0,15A, <8ns	31a	Hit	BAW62, BAX95, 1N4148..49, 1N4446..49++
1S2076A	Si-Di	=1S2076: 70V	31a		BAW62, BAX95, 1N4148..49, 1N4446..49++
1S208	Si-Di	Gl, Uni, 250V, 0,4A	34	Njr	BY128..127, BY133..134, 1N4004..07, ++
1S2080[Hitachi]	Si-Di	Gl, Uni, 200V, 1,1A	31a	Hit	BY133..135, BY226..227, 1N4003..07, ++
1S2081[Hitachi]	Si-Di	=1S2080[Hitachi]: 400V	31a		BY133..135, BY226..227, 1N4003..07, ++
1S2062(A)[Texas]	Z-Di	=1S2080[Texas]: 8,2V	31a	Tix	→1S2030

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1S2082[Hitachi]	Si-Di	=1S2080[Hitachi]: 600V	31a		BY133..135, BY226..227, 1N4003..07,++
1S2083	Si-Di	Gl-L, 100V, 20A[Tc=115°)	75a	Hit	1N3492..3495
1S2083R	Si-Di	=1S2083:	75b		DS25-.., 1N3492R..3495R
1S2084	Si-Di	Gl-L, 1000V, 10A(Tc=128°)	32a	Hit	1N3768, 1N4529..4530
1S2085(A)	C-Di	VHF/UHF-AFC, Tuning	31a	Nec	BB105, BB205, BB305, BB405, BB505++
1S2086(A)	C-Di	VHF/UHF-AFC, Tuning	31a	Nec	BB105, BB205, BB305, BB405, BB505++
1S2087(A)	C-Di	VHF/UHF-AFC, Tuning	31a	Nec	BB105, BB205, BB305, BB405, BB505++
1S2088(A)	C-Di	VHF/UHF-AFC, Tuning	31a	Nec	BB105, BB205, BB305, BB405, BB505++
1S2089	C-Di	VHF/UHF-O/M/AFC, Tuning	Koax	Nec	—
1S209	Si-Di	=1S208: 450V	34		BY126..127, BY133..134, 1N4005..07,++
1S2090	C-Di	UHF-AFC	31a	Hit	BA121, BB117, BB417, 1SV89
1S2091(A)[Texas]	Z-Di	=1S2030[Texas]: 9,1V	31a	Tix	→1S2030
1S2091[Toshiba]	Si-Di	CTV-HA-Diskr., 175V, 0,03A, <100ns	31a	Tos	BA195, BA197..198, BAV20..21, ++
1S2092	Si-Di	Uni, 125V, 0,03A, <100ns	31a	Tos	BA195, BA197..198, BAV19..21, ++
1S2093	Diac	Ub=26..38V, Ib<0,05mA, Itsm=2A	31	Tos	1N5761, N413M, BR100, D3202Y, DO201YR
1S2094	Si-Di	VHF/UHF-AFC	31a	Tos	BA121, BB117, BB417, 1SV89
1S2095	Si-Di	SS, 55V, 0,25A, <8ns	31a	Tos	BAW62, BAX95, 1N4148..49, 1N4446..49++
1S2095A	Si-Di	=1S2095: 75V	31a		BAW82, BAX95, 1N4148..49, 1N4446..49++
1S2097	Si-Di	SS, 225V, 0,03A, <4ns	31a	Tos	—
1S2098	Si-Di	SS, 175V, 0,04A, <4ns	31a	Tos	—
1S2099	Si-Di	SS, 125V, 0,05A, <4ns	31a	Tos	BA203
1S21	Ge-Di	Dual-Gl, 380V, 0,3A		Tos	—
1S210	Si-Di	=1S208: 650V	34		BY127, BY133, BY227, 1N4006..07,++
1S2100(A)[Texas]	Z-Di	=1S2030[Texas]: 10V	31a	Tix	→1S2030
1S2107(A)[Tosh.]	Z-Di	3,9V, 0,25W, 10%, (A=5%)	31a	Tos	BZX55/.., BZX79/.., ZPD.., 1N5228..48,++
1S2108(A)[Tosh.]	Z-Di	=1S2107[Tosh.]: 4,3V	31a		—
1S2109(A)[Tosh.]	Z-Di	=1S2107[Tosh.]: 4,7V	31a		—
1S211	Si-Di	=1S208: 850V	34		BY127, BY133, BY227, 1N4007,++
1S2110(A)[Texas]	Z-Di	=1S2030[Texas]: 11V	31a	Tix	→1S2030
1S2110(A)[Tosh.]	Z-Di	=1S2107[Tosh.]: 5,1V	31a	Tos	→1S2107
1S2111(A)[Tosh.]	Z-Di	=1S2107[Tosh.]: 5,6V	31a		—
1S2112(A)[Tosh.]	Z-Di	=1S2107[Tosh.]: 6,2V	31a		—
1S2113(A)[Tosh.]	Z-Di	=1S2107[Tosh.]: 6,8V	31a		—
1S2114(A)[Tosh.]	Z-Di	=1S2107[Tosh.]: 7,5V	31a		—
1S2115(A)[Tosh.]	Z-Di	=1S2107[Tosh.]: 8,2V	31a		—
1S2116(A)[Tosh.]	Z-Di	=1S2107[Tosh.]: 9,1V	31a		—
1S2117(A)[Tosh.]	Z-Di	=1S2107[Tosh.]: 10V	31a		—
1S2118(A)[Tosh.]	Z-Di	=1S2107[Tosh.]: 11V	31a		—
1S2119(A)[Tosh.]	Z-Di	=1S2107[Tosh.]: 12V	31a		—
1S212	Ref-Di	8..9V, 0,3W	≈34	Tos	—
1S2120(A)[Texas]	Z-Di	=1S2030[Texas]: 12V	31a	Tix	→1S2030
1S2120(A)[Tosh.]	Z-Di	=1S2107[Tosh.]: 13V	31a	Tos	→1S2107
1S2121(A)[Tosh.]	Z-Di	=1S2107[Tosh.]: 15V	31a		—
1S2122(A)[Tosh.]	Z-Di	=1S2107[Tosh.]: 16V	31a		—
1S2123(A)[Tosh.]	Z-Di	=1S2107[Tosh.]: 18V	31a		—
1S2124	Si-Di	Gl, Uni, 300V, 0,5A	31a	Nec	BY126..127, BY133..134, 1N4004..07,++
1S2125	Z-Di	5,4..6,6V, 0,25W	31	Nec	BZX55/.., BZX79/.., ZPD.., 1N5232..43,++
1S2126	Z-Di	=1S2125: 7,5..10V	31	Nec	—
1S2127	Z-Di	=1S2125: 10,8..13,2V	31	Nec	—
1S2128[NEC]	Z-Di	5,4..6,6V, 1W	34	Fui,Nec	BZW22/.., BZX61/.., ZPY.., 1N5919..53,++
1S2129[NEC]	Z-Di	=1S2128[NEC]: 7,5..10V	34		—
1S213	Ref-Di	8..9V, 0,3W	≈34	Tos	—
1S2130(A)[Texas]	Z-Di	=1S2030[Texas]: 13V	31a	Tix	→1S2030
1S2130[NEC]	Z-Di	=1S2128[NEC]: 10,8..13,2V	34		—
1S2131[NEC]	Z-Di	=1S2128[NEC]: 17..20V	34	Fui,Nec	→1S2128
1S2132[NEC]	Z-Di	=1S2128[NEC]: 80..115V	34		—
1S2133[NEC]	Z-Di	=1S2128[NEC]: 115..140V	34		—
1S2134	Si-Di	SS, 40V, 45mA, <7ns	31a	Fui,Hit,Nec	BA318, BAY38, 1N4305, 1N4148..49,++
1S2135	Si-Di	SS, 70V, 0,25A, <7ns	31a	Fui,Hit,Nec	BAW82, BAX95, 1N4446..49, 1N4148..49+
1S2136	Z-Di	5,4..6,6V, 0,25W	31	Hit	BZX55/.., BZX79/.., ZPD.., 1N5232..43,++
1S2137	Z-Di	=1S2136: 7,5..10V	31		—
1S2138	Z-Di	=1S2136: 10,8..13,2V	31		—
1S2139(A...C)	C-Di	VHF-AFC/Tuning	31a	Njr	BB105, BB205, BB305, BB405, BB505++
1S214	Ref-Di	8..9V, 0,3W	≈34	Tos	—
1S2140	Si-Di	SS, 60V, 0,25A, <8ns	31a	Fui	BAW82, BAX95, 1N4448..49, 1N4148..49+
1S2142	C-Di	Dual, FM/VHF, Tuning/AFC	12j	Sak	BB104, BB204, BB304, MV104, ++

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1S2143	C-Di	Dual,FM/VHF,Tuning/AFC	12j	Sak	BB104, BB204, BB304, MV104, ++
1S2144(A...C)	Si-Di	SS, 40V, 0,15A, 5ns	31a	Sak	BA200..201, BAW46, BAX80, 1N4148..49+
1S2145	Si-Di	SS, 90V, 0,1A, <5ns	31a	Sak	BA219, 1N4446..49, 1N4148..49
1S2147(A....D)	C-Di	VHF-AFC/Tuning	31a	Sak	BA105, BA205, BA305, BA405, BA505++
1S2148	Si-Di	Gl, Dual, 100V, 1,5A	12j	Sak	2x(BY226..227, BY251..255, 1N5392..99++)
1S2148R...2149R	Si-Di	=1S2148:	12h		2x(BY226..227, BY251..255, 1N5393..99++)
1S2149	Si-Di	=1S2148: 200V	12j		2x(BY226..227, BY251..255, 1N5393..99++)
1S215	Ref-Di	8,9..9,9V, 0,3W	≈34	Tos	—
1S2150(A)[Texas]	Z-Di	=1S2030[Texas]: 15V	31a	Tix	→1S2030
1S216	Ref-Di	8,9..9,9V, 0,3W	≈34	Tos	—
1S2160(A)[Texes]	Z-Di	=1S2030[Texas]: 18V	31a	Tix	→1S2030
1S217	Ref-Di	8,9..9,9V, 0,3W	≈34	Tos	—
1S2175	GaAs-Di	SS, 7,5V, 0,05A	Koax	Nec	—
1S2176	Si-Di	kV-Gl, 6kV, 0,1A, <500ns	≈31a	Org	BYX90, 1N5183
1S2177	Si-Di	kV-Gl, 6kV, 0,3A, <500ns	≈31a	Org	—
1S2178	Si-Di	kV-Gl, 6kV, 0,5A, <500ns	≈31a	Org	—
1S2179	Si-Di	Gl, S, 1200V, 2A	≈31a	Org	BY228, BY246/1200, BY448, BY458
1S218	Si-Di	SS, 40V, 0,04A, <2ns	31a	Tos	BA218, BAX13, BAX91, 1N4148..49, ++
1S2180(A)[Texas]	Z-Di	=1S2030[Texas]: 18V	31a	Tix	→1S2030
1S2160[Origin]	Si-Di	kV-Gl, 12kV, 0,1A, <500ns	≈31a	Org	1N3052
1S2181[Origin]	Si-Di	kV-Gl, 36kV, 0,1A, <500ns	≈31a	Org	—
1S2182[Origin]	Si-Di	kV-Gl, 30kV, 0,1A, <500ns		Org	1N3061
1S2186	C-Di	VHF/UHF-Band-3	31a	Tos	BA244, BA282, BA284, BA482
1S2187	Si-Di	Schottky-Di, UHF-M, 2V, 30mA, 900MHz	31a	Tos	BA460..481, BAT19, BAT29
1S2188	C-Di	AFC, Tuning	31a	Hit	—
1S219	Ge-Di	TV-Damper-Di, 300V, 10A(ss)	≈34a	Tos	—
1S2190	Ref-Di	7,7..8,7V	2c	Nec	BZX51, 1N4780
1S2191	Ref-Di	7,7..8,7V	2c		BZX52, 1N4781
1S2192	Ref-Di	7,7..8,7V	2c		BZX53, 1N4782
1S2193	Ref-Di	7,7..8,7V	2c		BZX54, 1N4783
1S2194	Z-Di	5,4..6,6V, 0,25W	31a	Nec	BZX55/.., BZX79/.., ZPD.., 1N5232..43,++
1S2195	Z-Di	=1S2194: 7,5..10V	31a		—
1S2196	Z-Di	=1S2194: 10,8..13,2V	31a		—
1S2197(A)	C-Di	AFC, Tuning	31a	Hit	—
1S2196	Si-Di	Schottky-Di, UHF-M, 5V, 30mA, 855MHz	31a	Nec	BA460..481, BAR19, BAT29
1S2199[NEC]	Ge-Di	Tunnel-Di	34	Nec	—
1S22	Ge-Di	Gl, 380V, 0,3A		Tos	—
1S220	Z-Di	4,5V, 10%, 1W	34a	Tos	BZW22/.., BZX61/.., ZPY...1N5917..53,++
1S2200(A)[Texas]	Z-Di	=1S2030[Texas]: 20V	31a	Tix	→1S2030
1S2200[NEC]	Ge-Di	Tunnel-Di	44	Nec	—
1S2204	Si-Di	SS, 70V, 0,2A, <7ns	31a	Nec	BAW82, BAX95, 1N4446..49, 1N4148..49++
1S2206	C-Di	UHF-AFC	71a(4mm)	Nec	BA121, BB117, BB417, 1SV89
1S2207	C-Di	VHF-AFC	71a(4mm)	Nec	BA125, BB119, 1SV114, 1SV125
1S2206	C-Di	UHF-Tuning	71a(4mm)	Nec	BB105, BB205, BB305, BB405, BB505++
1S2209	C-Di	VHF-Tuning	71a(4mm)	Nec	BB105, BB205, BB305, BB405, BB505++
1S221	Z-Di	=1S220: 5,5V	34a		—
1S2210	Si-Di	Schottky-Di, SS, 11V, 0,02A	31a	Nec	BAT19, 1SS88, 1SS106
1S2211	Si-Di	Schottky-Di, SS, 33V, 35mA	31a	Nec	BAT81
1S2212	Si-Di	S, 30V, 0,1A, <100ns	31a	Nec	BAV17..20, BAX90, BAX94, 1N3070, ++
1S222	Z-Di	=1S220: 6,5V	34a		—
1S2220(A)[Texas]	Z-Di	=1S2030[Texas]: 22V	31a	Tix	→1S2030
1S2222	C-Di	VHF/UHF-Band-S	71a(4mm)	Nec	BA244, BA282, BA284, BA482
1S2223	Si-Di	Dual, Gl, 100V, 1,8A	12j	Inr	2x(BY251..255, BY259/150, 1N5060..82++)
1S2223R...2225R	Si-Di	=1S2223:	12h		2x(BY251..255, BY259/.., 1N5060..62++)
1S2224	Si-Di	=1S2223: 200V	12j		2x(BY251..255, BY259/300, 1N5060..62++)
1S2225	Si-Di	=1S2223: 400V	12j		2x(BY252..255, BY259/600, 1N5060..82++)
1S2226	Si-Di	Gl, Uni, 100V, 1A	31a	Inr	BY126..127, BY133..135, 1N4002..07,++
1S2227	Si-Di	=1S2226: 200V	31a		BY126..127, BY133..134, 1N4003..07,++
1S2228	Si-Di	=1S2226: 400V	31a		BY126..127, BY133..134, 1N4004..07,++
1S2229	Si-Di	=1S2226: 600V	31a		BY126..127, BY133..134, 1N4005..07,++
1S223	Z-Di	=1S220: 7,5V	34a		—
1S2230	Si-Di	=1S2226: 800V	31a		BY127, BY133, BY227, 1N4006..07,++
1S2231	Si-Di	=1S2226: 1000V	31a		BY127, BY133, BY227, 1N4007,++
1S2233	Si-Di	Gl, Uni, 800V, 1,5A	34b	Tos	BY226..227, BY253..255, 1N5397..99,++
1S2234	Si-Di	=1S2233: 800V	34b		BY227, BY254..255, 1N5398..99,++
1S2235	Si-Di	=1S2233: 1000V	34b		BY227, BY255, BYX88, 1N5399,++

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1S2236	C-Di	FM-AFC	31a	Tos	BA111, BA124, 1S2790, 1SV50,++
1S2237(B)	Si-Di	kV-Gl, 18kV, 2mA, <250ns		Tos	BY476, BY711
1S2238[Hitachi]	Si-Di	Gl, contr.av., 400V, 1,3A	31a	Hit	BYW53..56, 1N5060..5062
1S2238[Hitachi]	Si-Di	=1S2238: 600V	31a		BYW54..56, 1N5061..5062
1S224	Z-Di	=1S220: 8,5V	34a		—
1S2240(A)[Texas]	Z-Di	=1S2030[Texas]: 24V	31a	Tix	→1S2030
1S2240[Hitachi]	Si-Di	=1S2238: 800V	31a		BYW55..56, 1N5062
1S2241	Si-Di	Gl, contr.av., 400V, 1,1A	31a	Hit	BYW53..56, 1N5060..5062
1S2242	Si-Di	=1S2241: 600V	31a		BTW54..56, 1N5061..5062
1S2243	Si-Di	=1S2241: 800V	31a		BTW55..56, 1N5062
1S2244	Si-Di	Gl, S, 200V, 0,4A, <800ns	31a	Hit	BA157..159, BY204/4, BY206..207,++
1S2245	Si-Di	=1S2244: 400V	31a		BA157..159, BY204/4, BY207,++
1S2248	Si-Di	=1S2244: 800V	31a		BA158..159, BY204/8, BY207,++
1S2247	Si-Di	Gl-L, 500V, 600A(Tc=90°)		Hit	—
1S2248	Si-Di	=1S2247: 600V			—
1S2249	Si-Di	=1S2247: 800V			—
1S225	Z-Di	=1S220: 9,5V	34a		—
1S2250	Si-Di	=1S2247: 1000V			—
1S2251	Si-Di	=1S2247: 1200V			—
1S2252	Si-Di	=1S2247: 1500V			—
1S2253	Si-Di	=1S2247: 2000V			—
1S2254	Si-Di	=1S2247: 2500V			—
1S2255	Si-Di	=1S2247: 3000V			—
1S2258	Si-Di	Gl-L, 1200V, 250A(Tc=111°)		Hit	—
1S2257	Si-Di	=1S2256: 1500V			—
1S2258	Si-Di	=1S2256: 1600V			—
1S2259	Si-Di	=1S2258: 1800V			—
1S226	Z-Di	=1S220: 11V	34a		—
1S2260	Si-Di	=1S2258: 2000V			—
1S2261	Si-Di	Gl-L, 1200V, 800A(Tc=101°)		Hit	—
1S2262	Si-Di	=1S2261: 1600V			—
1S2263	Si-Di	=1S2261: 1800V			—
1S2264	Si-Di	=1S2261: 2000V			—
1S2265	Si-Di	=1S2261: 2500V			—
1S2266	Si-Di	=1S2261: 2600V			—
1S2267	C-Di	VHF-AFC	31a	Hit	BA125, BB119, 1SV114, 1S125
1S2268	C-Di	UHF-AFC	31a	Hit	BA121, BB117, BB417, 1SV89
1S2269	Si-Di	Gl, Uni, 400V, 1A	31a	Sak	BY126..127, BY133..134, 1N4004..07,++
1S227	Z-Di	=1S220: 12V	34a		—
1S2270(A)[Texas]	Z-Di	=1S2030[Texas]: 27V	31a	Tix	→1S2030
1S2270[Sanken]	Si-Di	Gl, Uni, 200V, 1,3A	31a	Sak	BY226..227, BY251..255, 1N5393..99,++
1S2271[Sanken]	Si-Di	=1S2270: 400V	31a		BY226..227, BY252..255, 1N5395..99,++
1S2272[Sanken]	Si-Di	=1S2270: 800V	31a		BY226..227, BY253..255, 1N5397..99,++
1S2273[Sanken]	Si-Di	=1S2270: 800V	31a		BY227, BY254+F8241..255, 1N5398..99,++
1S2274[Sanken]	Si-Di	=1S2270: 1000V	31a		BY227, BY255, BYX86, 1N5399,++
1S2277	Si-Di	Gl, S, 200V, 0,3A, <800ns	31a	Sak	BA157..159, BY204/4, BY206..207,++
1S2278	Si-Di	=1S2277: 400V	31a		BA157..159, BY204/4, BY207,++
1S2279	Si-Di	=1S2277: 800V	31a		BA158..159, BY204/8, BY207,++
1S228	Z-Di	=1S220: 13V	34a		—
1S2280	Si-Di	=1S2277: 800V	31a		BA159, BY204/8, BY208/800,++
1S2281	Si-Di	=1S2277: 1000V	31a		BA159, BY204/10, BY208/1000,++
1S2282(A)[Hit.]	Z-Di	2,5..3,5V, 10W(Tc=115°)	32b	Hit	BZX98/..., BZY93/..., ZX..., 1N2970..89
1S2283(A)[Hit.]	Z-Di	=1S2282: 3,4..4,6V	32b		—
1S2284(A)[Hit.]	Z-Di	=1S2282: 4,4..5,4V	32b		—
1S2285(A)[Hit.]	Z-Di	=1S2282: 5,2..6,8V	32b		—
1S2286(A)[Hit.]	Z-Di	=1S2282: 6,2..7,9V	32b		—
1S2267(A)[Hit.]	Z-Di	=1S2262: 7,7..8,7V	32b		—
1S2286(A)[Hit.]	Z-Di	=1S2282: 8,5..9,6V	32b		—
1S2269(A)[Hit.]	Z-Di	=1S2262: 9,4..10,6V	32b		—
1S229	Z-Di	=1S220: 14V	34a		—
1S2290(A)[Hit.]	Z-Di	=1S2282: 10,4..11,6V	32b		—
1S2291(A)[Hit.]	Z-Di	=1S2282: 11,4..12,7V	32b		—
1S2292(A)[Hit.]	Z-Di	=1S2282: 12,4..14,1V	32b		—
1S2293(A)[Hit.]	Z-Di	=1S2282: 13,5..15,6V	32b		—
1S2294(A)[Hit.]	Z-Di	=1S2282: 15,3..17,1V	32b		—
1S2295(A)[Hit.]	Z-Di	=1S2282: 16,8..19,1V	32b		—

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1S2296(A)[Hit.]	Z-Di	=1S2282: 18,8..21,2V	32b		—
1S2297(A)[Hit.]	Z-Di	=1S2282: 20,8..23,3V	32b		—
1S2298(A)[Hit.]	Z-Di	=1S2282: 22,7..25,6V	32b		—
1S2299(A)[Hit.]	Z-Di	=1S2282: 25,1..28,9V	32b		—
1S23	Ge-Di	=1S22: 300V		Tos	—
1S230	Z-Di	=1S220: 15V	34a		—
1S2300(A)[Hit.]	Z-Di	=1S2282: 28..32V	32b		—
1S2300(A)[Texas]	Z-Di	=1S2030[Texas]: 30V	31a	Tix	→1S2030
1S2301	Z-Di	1,4..2,6V, 1W	31a	Hit	BZW22/.., BZX61/.., ZPY.., 1N5913..18,++
1S2302	Z-Di	=1S2301: 2,4..3,6V	31a		—
1S2303	Z-Di	=1S2301: 3,4..4,6V	31a		—
1S2304	Z-Di	=1S2301: 4,4..5,4V	31a		—
1S2305	Diac	Ub=28..38V, Ib<0,2mA, Itsm=2A	31l	Hit	1N5761, N413M, D3202Y, BR100, DO201YR
1S2306	Si-Di	Gl, Uni, 600V, 1A	34b	Tos	BY126..127, BY133..134, 1N4005..07,++
1S2307	Si-Di	=1S2306: 800V	34b		BY127, BY133, BY228, 1N4006..07,++
1S2308	Si-Di	=1S2306: 1000V	34b		BY127, BY133, BY228, 1N4007,++
1S2309	Si-Di	=1S2306: 1500V	34b		BY228, BY400, BY448, EM516, GP10W
1S231	Z-Di	=1S220: 16V	34a		—
1S2310	Si-Di	Gl, Uni, 600V, 0,3A	31a	Tos	BA158..159, BY204/8, BY208/600,++
1S2311	Si-Di	=1S2310: 800V	31a		BA159, BY204/8, BY208/600,++
1S2312	Si-Di	=1S2310: 1000V	31a		BA159, BY204/10, BY208/1000,++
1S2313	Si-Di	Gl, Uni, 600V, 0,15A	31a	Tos	BA158..159, BY204/8, BY208/600,++
1S2314	Si-Di	=1S2313: 800V	31a		BA159, BY204/8, BY208/800,++
1S2315	Si-Di	=1S2313: 1000V	31a		BA159, BY204/10, BY208/1000,++
1S2316	Si-Di	Gl, S, 400V, 0,13A, <300ns	31a	Sak	BA157..159, BY204/4, BY208/600,++
1S2317	Si-Di	=1S2316: 600V	31a		BA158..159, BY204/8, BY208/600,++
1S2318	Si-Di	=1S2316: 800V	31a		BA159, BY204/8, BY208/600,++
1S2319	Si-Di	=1S2316: 1000V	31a		BA159, BY204/10, BY208/1000,++
1S232	Z-Di	=1S220: 17V	34a		—
1S2320	Si-Di	Gl, S, 300V, 5A, <300ns		Sak	(BY229/400, BY233/400, BY277/600,++)
1S2321	Si-Di	Gl, S, 400V, 1,5A, <300ns		Sak	(BY229/400, BY233/400, BY277/600,++)
1S2323	Si-Di	Gl, S, 600V, 0,4A, <600ns	31a	Hit	BA159, BY204/8, BY208/800, BY228,++
1S2324	Si-Di	=1S2323: 1000V	31a		BA159, BY204/10, BY208/1000, BY228++
1S2325	Si-Di	=1S2323: 1300V	31a		BY228, BY268..269, BY400, BY448
1S2326	Si-Di	=1S2323: 1500V	31a		BY228, BY269, BY400, BY448
1S2329	Si-Di	Gl, Uni, 400V, 0,3A	31a	Tos	BA147..159, BY204/4, BY207,++
1S233	Z-Di	=1S220: 18V	34a		—
1S2330(A)[Texas]	Z-Di	=1S2030[Texas]: 33V	31a	Tix	→1S2030
1S2331	Si-Di	Gl-L, 100V, 100A(Tc=130°)	73b	Org	D120/400, DS80-04A, DS85-01C
1S2332	Si-Di	=1S2331: 200V	73b		D120/400, DS80-04A, DS85-02C
1S2333	Si-Di	=1S2331: 300V	73b		D120/400, DS80-04A, DS85-04C
1S2334	Si-Di	=1S2331: 400V	73b		D120/400, DS80-04A, DS85-04C
1S2335	Si-Di	=1S2331: 600V	73b		D120/800, DS80-07A, DS85-06C
1S2336	Si-Di	=1S2331: 600V	73b		D120/800, DS80-11A, DS85-08C
1S2337	Si-Di	=1S2331: 1000V	73b		D120/1200, DS80-14A, DS85-10C
1S2339	C-Di	VHF-Tuning/AFC	31a	Njr	BB105, BB205, BB305, BB405, BB505++
1S234	Z-Di	=1S220: 19V	34a		—
1S2340	C-Di	AFC	7a	Tos	BA121, BA125, BB117, BB119,++
1S2348H	Si-Di	SS, 65V, 0,25A, <8ns	31a	Hit	BAW62, BAX95, 1N4446..48, 1N4148..49++
1S2349	Si-Di	Dual, Gl, 200V, 1,8A	12j	Shi	2x(BY228..227, BY251..255, 1N5060,++)
1S2349R..2350R	Si-Di	=1S2349:	12h		2x(BY228..227, BY251..255, 1N5060,++)
1S235	Z-Di	=1S220: 20V	34a		—
1S2350	Si-Di	=1S2349: 400V	12j		2x(BY226..227, BY252..255, 1N5060,++)
1S2351	Si-Di	Gl, S, 200V, 0,1A, <1,5µs	31a	Shi	BA157..159, BAY88..91, BY203/12,++
1S2352	Si-Di	=1S2351: 600V	31a		BA158..159, BAY89..91, BY203/12,++
1S2353	Si-Di	=1S2351: 600V	31a		BA159, BAY90..91, BY203/12,++
1S2354	Si-Di	=1S2351: 1000V	31a		BA159, BAY90..91, BY203/12,++
1S2355	Si-Di	=1S2351: 1500V	31a		BAY91, BY203/16, BY584, SHG1,5,++
1S2356	Si-Di	Gl, contr.av., 200V, 0,4A	31a	Shi	BYW52..58, 1N4245..4249
1S2357	Si-Di	=1S2356: 400V	31a		BYW53..58, 1N4246..4249
1S2358	Si-Di	Gl, contr.av., 200V, 0,8A	31a	Shi	BYW52..58, 1N4245..4249
1S2359	Si-Di	=1S2356: 400V	31a		BYW53..58, 1N4246..4249
1S236	Z-Di	=1S220: 22V	34a		—
1S2361*	Si-Di	Gl, Uni, 200V, 1A	31a	Shi	BY126..127, BY133..134, 1N4003..07,++
1S2362	Si-Di	=1S2361: 400V	31a		BY126..127, BY133..134, 1N4004..07,++
1S2363	Si-Di	=1S2361: 600V	31a		BY126..127, BY133..134, 1N4005..07,++

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1S2364	Si-Di	=1S2361: 800V	31a		BY127, BY133, BY227, 1N4006..07,++
1S2365	Si-Di	=1S2361: 1000V	31a		BY127, BY133, BY227, 1N4007,++
1S2366	Si-Di	Gl, S, 200V, 0,1A, <1,5µs	31a	Shi	BA157..159, BAY88..91, BY203/12,++
1S2367	Si-Di	=1S2366: 600V	31a		BA158..159, BAY89..91, BY203/12,++
1S2366	Si-Di	=1S2366: 800V	31a		BA159, BAY90..91, BY203/12,++
1S2369	Si-Di	=1S2368: 1000V	31a		BA159, BAY90..91, BY203/12,++
1S237	Z-Di	=1S220: 24V	34a		—
1S2370	Si-Di	=1S2366: 1500V	31a		BAY91, BY203/12, BY584, SHG1,5,++
1S2371(A)	Si-Br	Gl-Br, 100V, 1A		Shi	B250C1500, etc.
1S2372(A)	Si-Br	=1S2371: 200V			B250C1500, etc.
1S2373(A)	Si-Br	=1S2371: 400V			B250C1500, etc.
1S2374(A)	Si-Br	=1S2371: 600V			B250C1500, etc.
1S2375(A)	Si-Br	=1S2371: contr.av., 200V			—
1S2376(A)	Si-Br	=1S2371: contr.C8345av., 400V			—
1S2377	Si-Di	Dual, Gl, 100V, 1,8A	12j	Shi	2x(BY226..227, BY251..255, 1N5060,++)
1S2377R..2380R	Si-Di	=1S2377:	12h		2x(BY228..227, BY251..255, 1N5061,++)
1S2378	Si-Di	=1S2377: 200V	12j		2x(BY226..227, BY251..255, 1N5060,++)
1S2379	Si-Di	=1S2377: 400V	12j		2x(BY226..227, BY252..255, 1N5060,++)
1S236	Z-Di	=1S220: 25V	34a		—
1S2380	Si-Di	=1S2377: 800V	12j		2x(BY226..227, BY253..255, 1N5061,++)
1S2361	Si-Di	Dual, Gl, 100V, 1A	12j	Shi	2x(BY126..127, BY133..135, 1N4002,++)
1S2362	Si-Di	=1S2361: 200V	12j		2x(BY126..127, BY133..134, 1N4003,++)
1S2363	Si-Di	=1S2361: 400V	12j		2x(BY126..127, BY133..134, 1N4004,++)
1S2364	Si-Di	=1S2361: 600V	12j		2x(BY126..127, BY133..134, 1N4005,++)
1S2367H	Si-Di	SS, 130V, 0,25A, <10ns	31a	Hit	BA203, BAV14
1S239	Z-Di	=1S220: 27V	34a		—
1S2390	Si-Di	Gl, Uni, 50V, 1A	31a	Nec	BY128..127, BY133..135, 1N4001..07,++
1S2391	Si-Di	=1S2390: 100V	31a		BY126..127, BY133..135, 1N4002..07,++
1S2392	Si-Di	=1S2390: 200V	31a		BY126..127, BY133..134, 1N4003..07,++
1S2393	Si-Di	=1S2390: 300V	31a		BY126..127, BY133..134, 1N4004..07,++
1S2394	Si-Di	=1S2390: 400V	31a		BY126..127, BY133..134, 1N4004..07,++
1S2395	Si-Di	=1S2390: 500V	31a		BY126..127, BY133..134, 1N4005..07,++
1S2396	Si-Di	=1S2390: 600V	31a		BY128..127, BY133..134, 1N4005..07,++
1S2397	Si-Di	=1S2390: 700V	31a		BY127, BY133, BY227, 1N4006..07,++
1S2398	Si-Di	=1S2390: 800V	31a		BY127, BY133, BY227, 1N4008..07,++
1S2399	Si-Di	=1S2390: 900V	31a		BY127, BY133, BY227, 1N4007,++
1S24	Ge-Di	=1S22: 200V		Tos	—
1S240	Z-Di	=1S220: 30V	34a		—
1S2400	Si-Di	=1S2390: 1000V	31a		BY127, BY133, BY227, 1N4007,++
1S2401	Si-Di	Gl, Uni, 100V, 1A	31a	Hit	BY126..127, BY133135, 1N4002..07,++
1S2402	Si-Di	=1S2401: 200V	31a		BY126..127, BY133..134, 1N4003..07,++
1S2403	Si-Di	=1S2401: 400V	31a		BY126..127, BY133..134, 1N4004..07,++
1S2404	Si-Di	=1S2401: 600V	31a		BY126..127, BY133..134, 1N4005..07,++
1S2405	Si-Di	=1S2401: 800V	31a		BY127, BY133, BY227, 1N4006..07,++
1S2406	Si-Di	=1S2401: 1000V	31a		BY127, BY133, BY227, 1N4007,++
1S2407	Si-Di	=1S2401: 1200V	31a		BY127, BY133, BY227, GP10Q,++
1S2406	Si-Di	Gl, Uni, 50V, 2A	31a	Hit	BY228..227, BY251..255, 1N5060..62,++
1S2409	Si-Di	=1S2408: 100V	31a		BY226..227, BY251..255, 1N5060..62,++
1S241	Z-Di	=1S220: 33V	34a		—
1S2410	Si-Di	=1S2408: 200V	31a		BY226..227, BY251..255, 1N5060..82,++
1S2411	Si-Di	=1S2408: 300V	31a		BY226..227, BY252..255, 1N5060..62,++
1S2412	Si-Di	=1S2406: 400V	31a		BY226..227, BY252..255, 1N5060..62,++
1S2413	Si-Di	=1S2408: 500V	31a		BY226..227, BY253..255, 1N5061..62,++
1S2414	Si-Di	=1S2408: 600V	31a		BY226..227, BY253..255, 1N5061..62,++
1S2415	Si-Di	Gl, Uni, 50V, 2A	31a	Hit	BY228..227, BY251..255, 1N5060..62,++
1S2416	Si-Di	=1S2415: 100V	31a		BY226..227, BY251..255, 1N5060..62,++
1S2417	Si-Di	=1S2415: 200V	31a		BY226..227, BY251..255, 1N5060..62,++
1S2418	Si-Di	=1S2415: 300V	31a		BY226..227, BY252..255, 1N5060..62,++
1S2419	Si-Di	=1S2415: 400V	31a		BY226..227, BY252..255, 1N5060..62,++
1S242	Z-Di	=1S220: 36V	34a		—
1S2420	Si-Di	=1S2415: 500V	31a		BY226..227, BY253..255, 1N5061..62,++
1S2421	Si-Di	=1S2415: 600V	31a		BY226..227, BY253..255, 1N5061..62,++
1S2422	Si-Di	Gl-L, 50V, 20A(Tc=115°)	75a	Hit	1N3491..3495
1S2422R..2427R	Si-Di	=1S2422:	75b		DS25-..A
1S2423	Si-Di	=1S2422: 100V	75a		1N3492..3495
1S2424	Si-Di	=1S2422: 200V	75a		1N3493..3495

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1S2425	Si-Di	=1S2422: 300V	75a		1N3494..3495
1S2426	Si-Di	=1S2422: 400V	75a		1N3495
1S2427	Si-Di	=1S2422: 500V	75a		—
1S2428(R)	Si-Di	Gl-L, 50V, 15A(Tc=115°)		Hit	—
1S2429(R)	Si-Di	=1S2428: 100V			—
1S243	Z-Di	=1S220: 39V	34a		—
1S2430(R)	Si-Di	=1S2428: 200V			—
1S2431(R)	Si-Di	=1S2428: 300V			—
1S2432(R)	Si-Di	=1S2428: 400V			—
1S2433(R)	Si-Di	=1S2428: 500V			—
1S2434	Si-Di	Gl-L, 50V, 12A(Tc=120°)	32a	Hit	1N3765..3768, 1N4525..4530
1S2434R...2439R	Si-Di	=1S2434:	32b		D24/..C, 1N3785R..3768R
1S2435	Si-Di	=1S2434: 100V	32a		1N3765..3768, 1N4525..4530
1S2436	Si-Di	=1S2434: 200V	32a		1N3765..3768, 1N4525..4530
1S2437	Si-Di	=1S2434: 300V	32a		1N3765..3768, 1N4526..4530
1S2438	Si-Di	=1S2434: 400V	32a		1N3765..3768, 1N4526..4530
1S2439	Si-Di	=1S2434: 500V	32a		1N3765..3768, 1N4527..4530
1S244	Z-Di	=1S220: 43V	34a		—
1S2440	Si-Di	Gl-L, 50V, 25A(Tc=120°)	75a	Hit	1N3491..3495
1S2440R...2445R	Si-Di	=1S2440:	75b		DS25-A
1S2441	Si-Di	=1S2440: 100V	75a		1N3492..3495
1S2442	Si-Di	=1S2440: 200V	75a		1N3493..3495
1S2443	Si-Di	=1S2440: 300V	75a		1N3494..3495
1S2444	Si-Di	=1S2440: 400V	75a		1N3495
1S2445	Si-Di	=1S2440: 500V	75a		—
1S2445R...2451R	Si-Di	=1S2446:	32b		D24/..C, 1N3765R..3768R
1S2446	Si-Di	Gl-L, 50V, 25A(Tc=120°)	32a	Hit	1N3765..3766, 1N4525..4530
1S2447	Si-Di	=1S2446: 100V	32a		1N3765..3768, 1N4525..4530
1S2446	Si-Di	=1S2446: 200V	32a		1N3765..3768, 1N4525..4530
1S2449	Si-Di	=1S2446: 300V	32a		1N3765..3768, 1N4526..4530
1S245	Z-Di	=1S220: 45V	34a		—
1S2450	Si-Di	=1S2446: 400V	32a		1N3765..3768, 1N4526..4530
1S2451	Si-Di	=1S2446: 500V	32a		1N3765..3768, 1N4527..4530
1S2452	Ref-Di	6..7V, 0,25W	2c	Tos	BZV10, BZV27, 1N4580
1S2453	Ref-Di	6..7V, 0,25W	2c		BZV11, BZV26, 1N4581
1S2454	Ref-Di	6..7V, 0,25W	2c		BZV12, BZV29, 1N4582
1S2455	Si-Di	Gl, Uni, 100V, 2,5A	31a	Hit	BY251..255, BV259/150, 1N5402..08,++
1S2456	Si-Di	=1S2455: 200V	31a		BY251..255, BY259/300, 1N5402..08,++
1S2457	Si-Di	=1S2455: 400V	31a		BY252..255, BY259/600, 1N5404..08,++
1S2458	Si-Di	=1S2455: 600V	31a		BY253..255, BY259/600, 1N5406..08,++
1S2459	Si-Di	=1S2455: 800V	31a		BY254..255, BY259/900, 1N5407..08,++
1S246	Z-Di	=1S220: 47V	34a		—
1S2460	Si-Di	Dem, Uni, 70V, 0,1A	31a	Tos	BA147/100, BAY19..21, 1N5606..09,++
1S2461	Si-Di	=1S2460: 120V	31a		BA147/150, BAY20..21, 1N5808..09,++
1S2462	Si-Di	=1S2460: 220V	31a		BA147/230, BAY21, BAY46, BAY68,++
1S2463	Si-Di	=1S2460: 320V	31a		BA147/3+F845300, BAY21, BAY46, BAY86,++
1S2464(R)	Si-Di	Gl-L, 200V, 15A(Tc=120°)		Sak	—
1S2468	Si-Di	kV-Gl, 38kV, 0,02A		Sak	—
1S2469	Si-Di	kV-Gl, 16kV, 0,02A	≈31a	Sak	CY20, HS13
1S247	Z-Di	=1S220: 50V	34a		—
1S2470	Si-Di	=1S2469: 12kV	≈31a		HS10
1S2471	Si-Di	SS, 90V, 0,13A, <4ns	31a	Rhm	BA219, 1N4148..49, 1N4446..4449,++
1S2472	Si-Di	SS, 55V, 0,12A, <4ns	31a	Rhm	BAW62, BAX95, 1N4148..49, 1N4446..49++
1S2473	Si-Di	SS, 40V, 0,11A, <4ns	31a	Rhm	BAW62, BAX95, 1N4148..49, 1N4446..49++
1S2474	Z-Di	0,6..0,6V, 0,75W	2d	Stl	BZW22/.., BZX61/.., ZPY.., 1N5913..56,++
1S2474R...2530R	Z-Di	=1S2474..2530:	2c		—
1S2475	Z-Di	=1S2474: 1,3..1,7V	2d		—
1S2476	Z-Di	=1S2474: 1,69..1,9V	2d		—
1S2477	Z-Di	=1S2474: 1,68..2,1V	2d		—
1S2476	Z-Di	=1S2474: 2,09..2,31V	2d		—
1S2479	Z-Di	=1S2474: 2,28..2,55V	2d		—
1S246	Z-Di	=1S220: 52V	34a		—
1S2480	Z-Di	=1S2474: 2,54..2,65V	2d		—
1S2461	Z-Di	=1S2474: 2,83..3,15V	2d		—
1S2482	Z-Di	=1S2474: 3,13..3,47V	2d		—
1S2483	Z-Di	=1S2474: 3,42..3,76V	2d		—

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1S2484	Z-Di	=1S2474: 3,7..4,1V	2d		—
1S2485	Z-Di	=1S2474: 4,08..4,52V	2d		—
1S2486	Z-Di	=1S2474: 4,47..4,94V	2d		—
1S2487	Z-Di	=1S2474: 4,84..5,36V	2d		—
1S2488	Z-Di	=1S2474: 5,32..5,9V	2d		—
1S2489	Z-Di	=1S2474: 5,89..6,51V	2d		—
1S249	Z-Di	=1S220: 56V	34a		—
1S2490	Z-Di	=1S2474: 6,48..7,14V	2d		—
1S2491	Z-Di	=1S2474: 7,12..7,86V	2d		—
1S2492	Z-Di	=1S2474: 7,79..8,63V	2d		—
1S2493	Z-Di	=1S2474: 8,62..9,56V	2d		—
1S2494	Z-Di	=1S2474: 9,5..10,5V	2d		—
1S2495	Z-Di	=1S2474: 10,4..11,6V	2d		—
1S2496	Z-Di	=1S2474: 11,4..12,6V	2d		—
1S2497	Z-Di	=1S2474: 12,3..13,7V	2d		—
1S2498	Z-Di	=1S2474: 13,2..15,8V	2d		—
1S2499	Z-Di	=1S2474: 15,2..17V	2d		—
1S25	Ge-Di	=1S22: 100V		Tos	—
1S250	Z-Di	=1S220: 62V	34a		—
1S2500	Z-Di	=1S2474: 16,9..19V	2d		—
1S2501	Z-Di	=1S2474: 18,8..21V	2d		—
1S2502	Z-Di	=1S2474: 20,9..23,1V	2d		—
1S2503	Z-Di	=1S2474: 22,8..25,5V	2d		—
1S2504	Z-Di	=1S2474: 25,4..28,5V	2d		—
1S2505	Z-Di	=1S2474: 28,3..31,5V	2d		—
1S2508	Z-Di	=1S2474: 31,3..34,7V	2d		—
1S2507	Z-Di	=1S2474: 34,2..37,8V	2d		—
1S2508	Z-Di	=1S2474: 37..41V	2d		—
1S2509	Z-Di	=1S2474: 40,8..45,2V	2d		—
1S251	Z-Di	=1S220: 68V	34a		—
1S2510	Z-Di	=1S2474: 44,7..49,4V	2d		—
1S2511	Z-Di	=1S2474: 48,4..53,8V	2d		—
1S2512	Z-Di	=1S2474: 53,2..59V	2d		—
1S2513	Z-Di	=1S2474: 58,9..65,1V	2d		—
1S2514	Z-Di	=1S2474: 84,6..71,4V	2d		—
1S2515	Z-Di	=1S2474: 71,2..78,8V	2d		—
1S2516	Z-Di	=1S2474: 77,9..86,3V	2d		—
1S2517	Z-Di	=1S2474: 86,2..95,6V	2d		—
1S2518	Z-Di	=1S2474: 95..105V	2d		—
1S2519	Z-Di	=1S2474: 104..116V	2d		—
1S252	Z-Di	=1S220: 75V	34a		—
1S2520	Z-Di	=1S2474: 114..126V	2d		—
1S2521	Z-Di	=1S2474: 123..137V	2d		—
1S2522	Z-Di	=1S2474: 132..158V	2d		—
1S2523	Z-Di	=1S2474: 152..170V	2d		—
1S2524	Z-Di	=1S2474: 189..190V	2d		—
1S2525	Z-Di	=1S2474: 186..210V	2d		—
1S2526	Z-Di	=1S2474: 209..231V	2d		—
1S2527	Z-Di	=1S2474: 228..255V	2d		—
1S2528	Z-Di	=1S2474: 254..285V	2d		—
1S2529	Z-Di	=1S2474: 283..315V	2d		—
1S253	Z-Di	=1S220: 82V	34a		—
1S2530	Z-Di	=1S2474: 313..347V	2d		—
1S2531	Z-Di	0,8..0,8V, 0,25W	2d	Sti	BZX55/.., BZX79/.., ZPD.., 1N5221..71,++
1S2531R..2575R	Z-Di	=1S2531:	2c		—
1S2532	Z-Di	=1S2531: 1,3..1,7V	2d		—
1S2533	Z-Di	=1S2531: 1,89..1,9V	2d		—
1S2534	Z-Di	=1S2531: 1,86..2,1V	2d		—
1S2535	Z-Di	=1S2531: 2,09..2,31V	2d		—
1S2536	Z-Di	=1S2531: 2,28..2,55V	2d		—
1S2537	Z-Di	=1S2531: 2,54..2,85V	2d		—
1S2538	Z-Di	=1S2531: 2,83..3,15V	2d		—
1S2539	Z-Di	=1S2531: 3,13..3,47V	2d		—
1S254	Z-Di	=1S220: 91V	34a		—
1S2540	Z-Di	=1S2531: 3,42..3,78V	2d		—
1S2541	Z-Di	=1S2531: 3,7..4,1V	2d		—

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1S2542	Z-Di	=1S2531: 4,08..4,52V	2d		—
1S2543	Z-Di	=1S2531: 4,47..4,94V	2d		—
1S2544	Z-Di	=1S2531: 4,84..5,36V	2d		—
1S2545	Z-Di	=1S2531: 5,32..5,9V	2d		—
1S2548	Z-Di	=1S2531: 5,89..6,51V	2d		—
1S2547	Z-Di	=1S2531: 6,46..7,14V	2d		—
1S2548	Z-Di	=1S2531: 7,12..7,88V	2d		—
1S2549	Z-Di	=1S2531: 7,79..8,63V	2d		—
1S255	Z-Di	=1S220: 100V	34a		—
1S2550	Z-Di	=1S2531: 8,62..9,56V	2d		—
1S2551	Z-Di	=1S2531: 9,5..10,5V	2d		—
1S2552	Z-Di	=1S2531: 10,4..11,6V	2d		—
1S2553	Z-Di	=1S2531: 11,4..12,6V	2d		—
1S2554	Z-Di	=1S2531: 12,3..13,7V	2d		—
1S2555	Z-Di	=1S2531: 13,2..15,8V	2d		—
1S2556	Z-Di	=1S2531: 15,2..17V	2d		—
1S2557	Z-Di	=1S2531: 16,9..19V	2d		—
1S2558	Z-Di	=1S2531: 18,8..21V	2d		—
1S2559	Z-Di	=1S2531: 20,9..23,1V	2d		—
1S256	Z-Di	=1S220: 105V	34a		—
1S2560	Z-Di	=1S2531: 22,8..25,5V	2d		—
1S2561	Z-Di	=1S2531: 25,4..28,5V	2d		—
1S2562	Z-Di	=1S2531: 28,3..31,5V	2d		—
1S2563	Z-Di	=1S2531: 31,3..34,7V	2d		—
1S2564	Z-Di	=1S2531: 34,2..37,3V	2d		—
1S2565	Z-Di	=1S2531: 37..41V	2d		—
1S2566	Z-Di	=1S2531: 40,8..45,2V	2d		—
1S2567	Z-Di	=1S2531: 44,7..49,4V	2d		—
1S2566	Z-Di	=1S2531: 48,4..53,6V	2d		—
1S2569	Z-Di	=1S2531: 53,2..59V	2d		—
1S257	Z-Di	=1S220: 110V	34a		—
1S2570	Z-Di	=1S2531: 58,9..65,1V	2d		—
1S2571	Z-Di	=1S2531: 64,6..71,4V	2d		—
1S2572	Z-Di	=1S2531: 71,2..78,8V	2d		—
1S2573	Z-Di	=1S2531: 77,9..86,3V	2d		—
1S2574	Z-Di	=1S2531: 88,2..95,8V	2d		—
1S2575	Z-Di	=1S2531: 95..105V	2d		—
1S256	Z-Di	=1S220: 120V	34a		—
1S2568	C-Di	VHF-Band-S	31a	Njr	BA182, BA243, BA283, BA483..484, ++
1S2569	Si-Di	Uni, 50V, 0,75A	31a	Hit	BY128..127, BY133..135, 1N4001..07, ++
1S259	Z-Di	=1S220: 130V	34a		—
1S2590	Si-Di	=1S2589: 100V	31a		BY126..127, BY133..135, 1N4002..07, ++
1S2591	Si-Di	=1S2589: 200V	31a		BY126..127, BY133..134, 1N4003+F8520..07, ++
1S2592	Si-Di	Gl, S, 800V, 1A, <800ns	31a	Hit	BY231/800, BY400, MR817, RGP10K, ++
1S2593	Si-Di	=1S2592: 1000V	31a		BY231/1000, BY400, MR818, RGP10M, ++
1S2594	Si-Di	=1S2592: 1300V	31a		BY231/1400, BY228, BY400, BY448
1S2595	Si-Di	=1S2592: 1500V	31a		BY231/1500, BY228, BY400, BY448
1S2596	Si-Di	Gl, S, 200V, 2A, <800ns	31a	Hit	BY218/200, BY296..299, BYW32..36, ++
1S2597	Si-Di	=1S2596: 400V	31a		BY218/400, BY298..299, BYW34..36, ++
1S2598	Si-Di	=1S2596: 600V	31a		BY218/800, BY228, BY299, BYW36, ++
1S26	Ge-Di	Gl-L, 100V, 3,5A	~34a	Njr	—
1S260	Z-Di	=1S220: 140V	34a		—
1S2602	Si-Di	Gl, contr.av., 200V, 1A	31a	Nec	BYW52..56, 1N4245..49, 1N5060..62
1S2803	Si-Di	=1S2602: 300V	31a		BYW53..56, 1N4246..49, 1N5080..62
1S2804	Si-Di	=1S2602: 400V	31a		BYW53..56, 1N4246..49, 1N5060..62
1S2605	Si-Di	=1S2602: 500V	81a		BYW54..56, 1N4247..49, 1N5061..62
1S2606	Si-Di	=1S2602: 600V	31a		BYW54..56, 1N4247..49, 1N5061..62
1S2607	Si-Di	=1S2602: 700V	31a		BYW55..56, 1N4248..49, 1N5062
1S2606	Si-Di	=1S2602: 800V	31a		BYW55..58, 1N4248..49, 1N5062
1S2609	Si-Di	=1S2602: 900V	31a		BYW56, 1N4249
1S281	Z-Di	=1S220: 150V	34a		—
1S2610	Si-Di	=1S2602: 1000V	31a		BYW58, 1N4249
1S2611	Si-Di	=1S2602: 1100V	31a		SSiB9860A
1S2612	Si-Di	=1S2602: 1200V	31a		SSiB9860A
1S2813	Si-Di	=1S2602: 1300V	31a		SSiB9860A
1S2814	Si-Di	=1S2602: 1400V	31a		SSiB9860A

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1S2615	Si-Di	Gl, S, 600V, 1A, <250ns	34b	Tos	BY201/6, BYV14..16, BYX55/600, ++
1S2616	Si-Di	=1S2615: <850ns	34b		BY201/6, BYV14..16, BYX55/600, ++
1S2617	Si-Di	=1S2615: <900ns	34b		BY201/6, BYV14..16, BYX55/600, ++
1S2618	Si-Di	Gl, S, 600V, 1A, <600ns	31a	Hit	BY245/600, BY231/800, MR617, RGP10K, ++
1S2619	Si-Di	kV-Gl, 8kV, 0,04A	31a	Inr	1N5184
1S262	Z-Di	4,5V, 10%, 10W	32a	Tos	BZX98/.., BZY93/.., ZL.., 1N2970..3011 ++
1S2620	Si-Di	kV-Gl, 16kV, 0,04A	31a	Inr	1N3054
1S2621	Si-Di	kV-Gl, 24kV, 0,04A	31a	Inr	1N3058
1S2622	Si-Di	kV-Gl, 32kV, 0,04A	31a	Inr	1N3061
1S2628	Si-Di	Gl/S-L, 100V, 5,5A, <300ns	32b	Fjd	1N3880R..3883R
1S2629	Si-Di	=1S2628: 200V	32b		1N3881R..3883R
1S263	Z-Di	=1S262: 5,5V	32a		—
1S2630	Si-Di	Gl/S-L, 100V, 8A(Tc=70°), <300ns	32	Fjd	BYV30/100, BYW30/100, BYX61/100, ++
1S2831	Si-Di	=1S2630: 200V	32		BYV30/200, BYW30/200, BYX61/200, ++
1S2632	Si-Di	Gl/S-L, 100V, 18A(Tc=70°), <300ns	73	Fjd	—
1S2633	Si-Di	=1S2832: 200V	73		—
1S2634	Si-Di	Gl/S-L, 100V, 46A(Tc=70°), <400ns	73	Fjd	—
1S2635	Si-Di	=1S2634: 200V	73		—
1S2636	Si-Di	Gl/S-L, 100V, 95A(Tc=70°), <400ns	73	Fjd	—
1S2637	Si-Di	=1S2836: 200V	73		—
1S2636	C-Di	VHF-AFC	31a	Hit	BA125, BB119, 1SV114, 1SV125
1S2639	Si-Di	Gl-L, 1400V, 50A(Tc=125°)	73b	Rhm	—
1S284	Z-Di	=1S262: 6,5V	32a		—
1S2640	Si-Di	=1S2639: 1800V	73b		—
1S2841	Si-Di	=1S2639: 2000V	73b		—
1S2842	Si-Di	=1S2639: 2500V	73b		—
1S2843	Si-Di	=1S2639: 3000+C6850V	73b		—
1S2644	Si-Di	Gl-L, 1400V, 80A(Tc=115°)	73b	Rhm	—
1S2845	Si-Di	=1S2644: 1600V	73b		—
1S2646	Si-Di	=1S2644: 2000V	73b		—
1S2847	Si-Di	=1S2644: 2500V	73b		—
1S2646	Si-Di	=1S2844: 3000V	73b		—
1S2849	Si-Di	Gl-L, 400V, 100A(Tc=90°)	73b	Rhm	1N3291R..3297R
1S265	Z-Di	=1S262: 7,5V	32a		—
1S2850	Si-Di	=1S2849: 600V	73b		1N3293R...3297R
1S2651	Si-Di	=1S2849: 600V	73b		1N3294R..3297R
1S2652	Si-Di	=1S2849: 1000V	73b		1N3295R..3297R
1S2653	Si-Di	=1S2649: 1200V	73b		1N3296R..3297R
1S2654	Si-Di	Gl-L, 600V, 210A(Tc=110°)	73b	Rhm	1N3740R..3744R
1S2655	Si-Di	=1S2854: 800V	73b		1N3741R..3744R
1S2656	Si-Di	=1S2654: 1000V	73b		1N3742R..3744R
1S2657	Si-Di	=1S2654: 1200V	73b		1N3743R...3744R
1S2656	Si-Di	=1S2654: 1400V	73b		1N3744R
1S2659	Si-Di	=1S2654: 1600V	73b		—
1S266	Z-Di	=1S262: 8,5V	32a		—
1S2660	Si-Di	Gl-L, 600V, 400A(Tc=100°)	73b		—
1S2881	Si-Di	=1S2660: 800V	73b		—
1S2662	Si-Di	=1S2660: 1000V	73b		—
1S2663	Si-Di	=1S2660: 1200V	73b		—
1S2684	Si-Di	=1S2660: 1400V	73b		—
1S2665	Si-Di	=1S2660: 1600V	73b		—
1S2666	Si-Di	Gl/S-L, 100V, 80A, <300ns	73b	Sak	—
1S2667	Si-Di	=1S2666: 200V	73b		—
1S2668	Si-Di	=1S2666: 250V	73b		—
1S2669	Si-Di	Gl/S-L, 100V, 8A(Tc=100°), <300ns		Sak	—
1S267	Z-Di	=1S282: 9,5V	32a		—
1S2670	Si-Di	=1S2669: 250V			—
1S2671	Si-Di	=1S2669: 400V			—
1S2672	Si-Di	Gl, S, 200V, 0,8A, <200ns	31a		BY201/2, BYT52D, BYX92/200, RGP10D
1S2673	Si-Di	=1S2672: 300V	31a		BY201/3, BYT52G, BYX92/300, RGP10G
1S2674	Si-Di	=1S2672: 400V	31a		BY201/4, BYT52G, BYX92/400, RGP10G
1S2675	Si-Di	=1S2672: 500V	31a		BY201/5, BYT52J, RGP10J
1S2676	Si-Di	=1S2672: 600V	31a		BY201/6, BYT52J, RGP10J
1S2677	Si-Di	=1S2872: 700V	31a		BYT52K, RGP10K
1S2678	Si-Di	=1S2872: 600V	31a		BYT52K, RGP10K
1S2679	Si-Di	=1S2872: 1000V	31a		BYT52M, RGP10M

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1S268	Z-Di	=1S262: 11V	32a		—
1S2685	Si-Di	VHF-Tuning	71a(4mm)	Hit	BB105, BB205, BB305, BB405, BB505++
1S2686	Si-Di	AFC	31a	Njr	—
1S2687	Si-Di	AFC	31a	Njr	—
1S2888	C-Di	AFC	31a	Njr	—
1S2689	Si-Di	AFC	31a	Njr	—
1S269	Z-Di	=1S262: 12V	32a		—
1S2692	Si-Di	VHF-Band-S	71a(4mm)	Hit	BA182, BA243, BA283, BA483..484, ++
1S27	Ge-Di	Gl-L, 70V, 10A		Njr	—
1S270	Z-Di	=1S282: 13V	32a		—
1S2701(R)	Si-Di	Gl-L, 100V, 100A(Tc=96°)		Nec	—
1S2702(R)	Si-Di	=1S2701: 200V			—
1S2703(R)	Si-Di	=1S2701: 300V			—
1S271	Z-Di	=1S262: 14V	32a		—
1S2711	Si-Di	Gl, 1500V, 1,5A	34a	Tos	BY228, BY255, BY400, BY448
1S2712	Si-Di	Gl, S, 1800V, 1,4A, <2,2µs	34b	Tos	—
1S2713	Si-Di	kV-Gl, 45kV, 2A		Tos	—
1S2714	Si-Di	Gl/S-L, 100V, 6A(Tc=100°), <200ns	32	Tos	1N3880..3883
1S2715	Si-Di	=1S2714: 200V	32		1N3881..3883
1S2718	Si-Di	=1S2714: 300V	32		1N3882..3883
1S2717	Si-Di	=1S2714: 400V	32		1N3883
1S2718	Si-Di	=1S2714: 800V	32		—
1S2719	Si-Di	Gl/S-L, 100V, 30A(Tc=100°), <200ns	32	Tos	1N3910..3913
1S272	Z-Di	=1S262: 15V	32a		—
1S2720	Si-Di	=1S2719: 200V	32		1N3911..3913
1S2721	Si-Di	=1S2719: 300V	32		1N3912..3913
1S2722	Si-Di	=1S2719: 400V	32		1N3913
1S2723	Si-Di	=1S2719: 600V	32		—
1S2724	Si-Di	Dual, 200V, 5A	22f	Sak	—
1S2724R..2726R	Si-Di	=1S2724	22n		—
1S2725	Si-Di	=1S2724: 400V	22f		—
1S2726	Si-Di	=1S2724: 800V	22f		—
1S273	Z-Di	=1S282: 16V	32a		—
1S274	Z-Di	=1S262: 17V	32a		—
1S2745	Si-Di	Gl, S, 750V, 2,5A, <1,3µs	34b	Tos	BY228, BY438, RGP30K
1S2748	Si-Di	=1S2745: 800V	34b		BY228, BY438, RGP30K
1S2747	Si-Di	=1S2745: 1000V	34b		BY228, BY438, RGP30M
1S275	Z-Di	=1S282: 18V	32a		—
1S2756	Si-Di	Gl, Uni, 400V, 1A, <2,5µs	31a	Tos	BY201/4, BYX55/600, RGP10G
1S2757	Si-Di	=1S2756: 800V	31a		BY201/6, BYX55/600, RGP10J
1S2758	Si-Di	Gl, Uni, 1000V, 3A	31a	Nec	BY255, BYW17/1000, G3M, 1N5408, ++
1S2759	Si-Di	=1S2758: 1200V	31a		BY255, BYW17/1200
1S276	Z-Di	=1S262: 19V	32a		—
1S2760	Si-Di	=1S2756: 50V	31a		BY261..255, BYW17/100, 1N5402..08, ++
1S2781	Si-Di	=1S2758: 100V	31a		BY251..255, BYW17/100, 1N5402..08, ++
1S2762	Si-Di	=1S2758: 200V	31a		BY251..255, BYW17/200, 1N5402..08, ++
1S2763	Si-Di	=1S2756: 300V	31a		BY252..255, BYW17/400, 1N5403..08, ++
1S2764	Si-Di	=1S2756: 400V	31a		BY252..255, BYW17/400, 1N5404..08, ++
1S2785	Si-Di	=1S2758: 500V	31a		BY253..255, BYW17/600, 1N5406..08, ++
1S2768	Si-Di	=1S2756: 800V	31a		BY253..255, BYW17/800, 1N5406..08, ++
1S2766A	Si-Di	=1S2766: contr.av.	31a		BYM56C, BYW18/600, BYW84..86
1S2787	Si-Di	=1S2756: 700V	31a		BY254..255, BYW17/800, 1N5407..08, ++
1S2767A	Si-Di	=1S2787: contr.av.	31a		BYM56D, BYW18/800, BYW85..86
1S2768	Si-Di	=1S2758: 800V	31a		BY254..255, BYW17/800, 1N5407..08, ++
1S2766A	Si-Di	=1S2766: contr.av.	31a		BYM56D, BYW18/800, BYW85..66
1S2769	Ref-Di	8..7V, 0,25W	2a	Nec	BZV10, BZV27, 1N4580
1S277	Z-Di	=1S282: 20V	32a		—
1S2770	Ref-Di	6..7V, 0,25W	2a		BZV10, BZV27, 1N4580
1S2771	Ref-Di	6..7V, 0,25W	2a		BZV11, BZV28, 1N4581
1S2772	Ref-Di	8..7V, 0,25W	2a		BZV12, BZV29, 1N4582
1S2773	Ref-Di	8..7V, 0,25W	2a		BZV13, BZV30, 1N4583
1S2774	Ref-Di	6..7V, 0,25W	2a		BZV14, BZV31, 1N4584
1S2775	Si-Di	Gl, Uni, 200V, 0,5A, <2µs	31a	Tos	BY295/200, BY408..407, BYX55/600, ++
1S2776	Si-Di	=1S2775: 400V	31a		BY295/400, BY407, BYX55/600, ++
1S2777	Si-Di	=1S2775: 800V	31a		BY295/800, BY407, BYX55/800, ++
1S2778	Si-Di	Gl, Uni, 200V, 2,7A	31a	Sak	BY251..255, GP30D, MR502..510, ++

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1S2779	Si-Di	=1S2778: 400V	31a		BY252..255, GP30G, MR504..510,++
1S278	Z-Di	=1S262: 22V	32a		—
1S2780	Si-Di	=1S2778: 600V	31a		BY253..255, GP30J, MR506..510,++
1S2781	Si-Di	=1S2778: 600V	31a		BY254..255, GP30K, MR506..510,++
1S2782	Si-Di	=1S2778: 1000V	31a		BY228, BY255, GP30M, MR510,++
1S2783	C-Di	Tuning	31a	Njr	—
1S2784	Si-Br	Gl-Br, 100V, 0,5A	42	Stl	B100C500, etc.
1S2785	Si-Br	=1S2784: 200V	42		B200C500, etc.
1S2786	Si-Br	=1S2784: 400V	42		B400C500, etc.
1S2787	Si-Di	SS, 40V, 0,05A, <3ns	31a	Rhm	BA318, BAY38, 1N4148..49, 1N4446..49++
1S2788	Si-Di	SS, 25V, 0,05A, <3ns	31a	Rhm	BA318, BAY38, 1N4148..49, 1N4446..49++
1S2789	C-Di	UHF-Tuning	71a(4mm)	Tos	BB105, BB205, BB305, BB405, BB505++
1S279	Z-Di	=1S282: 24V	32a		—
1S2790	C-Di	VHF-AFC	31a	Hit	BA125, BB119, 1SV114, 1SV125
1S2791	Si-Di	Schottky-Di, UHF-M, 5V, 30mA, 887MHz	31a	Hit	BA480..481, BAR18, BAT29
1S2792	Si-Di	Gl/S-L, 100V, 20A(Tc=90°), <300ns	32b	Sak	1N3900R..3903R
1S2793	Si-Di	=1S2792: 250V	32b		1N3902R..39033R
1S2794	Si-Di	=1S2792: 400V	32b		1N3903R
1S2795	Si-Di	Gl-L, 400V, 12A(Tc=40°)	32	Tos	—
1S2796	Si-Di	=1S2795: 600V	32		—
1S2797	Si-Di	=1S2795: 800V	32		—
1S2798	Si-Di	=1S2795: 1000V	32		—
1S2799	Si-Di	Gl-L, 100V, 150A(Tc=76°)	73	Inr	1N4587..4596
1S28	Ge-Di	Gl-L, 50V, 0,5A	≈34a	Njr	—
1S280	Z-Di	=1S262: 25V	32a		—
1S2800	Si-Di	=1S2799: 200V	73		1N4588..4596
1S2801	Si-Di	=1S2796: 300V	73		1N4589..4596
1S2802	Si-Di	=1S2799: 400V	73		1N4590..4596
1S2803	Si-Di	=1S2799: 600V	73		1N4592..4596
1S2804	Si-Di	=1S2799: 800V	73		1N4593..4596
1S2805	Si-Di	=1S2799: 1000V	73		1N4594..4596
1S2806	Si-Di	=1S2799: 1200V	73		1N4595..4596
1S2807	Si-Di	=1S2799: 1400V	73		1N4596
1S2808	Si-Di	=1S2799: 1600V	73		—
1S2809	Si-Di	Gl-L, 100V, 250A(Tc=74°)	73	Inr	1N3735..3744
1S281	Z-Di	=1S262: 27V	32a		—
1S2810	Si-Di	=1S2809: 200V	73		1N3736..3744
1S2811	Si-Di	=1S2809: 300V	73		1N3737..3744
1S2812	Si-Di	=1S2809: 400V	73		1N3738..3744
1S2813	Si-Di	=1S2809: 600V	73		1N3740..3744
1S2814	Si-Di	=1S2809: 600V	73		1N3741..3744
1S2815	Si-Di	=1S2809: 1000V	73		1N3742..3744
1S2816	Si-Di	=1S2809: 1200V	73		1N3743..3744
1S2817	Si-Di	=1S2809: 1400V	73		1N3744
1S2818	Si-Di	=1S2809: 1600V	73		—
1S2819	Si-Di	Gl-L, 600V, 500A(Tc=100°)	73	Inr	—
1S282	Z-Di	=1S262: 30V	32a		—
1S2820	Si-Di	=1S2819: 800V	73		—
1S2821	Si-Di	=1S2819: 1000V	73		—
1S2822	Si-Di	=1S2819: 1200V	73		—
1S2823	Si-Di	=1S2819 1400V	73		—
1S2824	Si-Di	=1S2819: 1600V	73		—
1S2825	Si-Di	=1S2819: 1800V	73		—
1S2826(A)	Si-Di	Gl, Uni, 100V, 1,5A	31a	Sak	BY228..227, BY251..255, 1N5401..08,++
1S2827(A)	Si-Di	=1S2826: 200V	31a		BY228..227, BY251..255, 1N5402..08,++
1S2828(A)	Si-Di	=1S2828: 400V	31a		BY226..227, BY252..255, 1N5404..08,++
1S2829(A)	Si-Di	=1S2826: 600V	31a		BY226..227, BY253..255, 1N5408..08,++
1S283	Z-Di	=1S262: 33V	32a		—
1S2830(A)	Si-Di	=1S2826: 800V	31a		BY227, BY254..255, 1N5407..08,++
1S2831(A)	Si-Di	=1S2626: 1000V	31a		BY227, BY228, BY255, 1N5408,++
1S2832	Si-Di	Gl, Uni, 200V, 1A	31a	Sak	BY126..127, BY228..227, 1N4003..07,++
1S2833	Si-Di	=1S2832: 600V	31a		BY127, BY227, GP10Q, 1N4006..07,++
1S2834	Si-Di	=1S2832: 1200V	31a		BY127, BY227, EM513, GP10Q,++
1S2835	Si-Di	SMD, Dual, SS, 35V, 0,15A, <4ns	35n	Nec	BAW86, BAW68
1S2836	Si-Di	=1S2835: 75V	35n		BAS35
1S2837	Si-Di	=1S2835:	35f		BAW64, BAW65, BAW87

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1S2838	Si-Di	=1S2835: 75V	35f		—
1S2839	Si-Di	Gl, Uni, 600V, 1A, 1,5µs	34b	Tos	BY201/6, BYX55/600, RGP10J,++
1S284	Z-Di	=1S262: 36V	32a		—
1S285	Z-Di	=1S262: 39V	32a		—
1S286	Z-Di	=1S262: 43V	32a		—
1S287	Z-Di	=1S262: 45V	32a		—
1S286	Z-Di	=1S262: 47V	32a		—
1S289	Z-Di	=1S262: 50V	32a		—
1S29	Ge-Di	=1S28: 150V	=34a	Njr	—
1S290	Z-Di	=1S262: 52V	32a		—
1S291	Z-Di	=1S262: 56V	32a		—
1S292	Z-Di	=1S262: 62V	32a		—
1S293	Z-Di	=1S262: 86V	32a		—
1S294	Z-Di	=1S262: 75V	32a		—
1S295	Z-Di	=1S262: 62V	32a		—
1S296	Z-Di	=1S262: 91V	32a		—
1S297	Z-Di	=1S262: 100V	32a		—
1S298	Z-Di	=1S262: 105V	32a		—
1S299	Z-Di	=1S262: 110V	32a		—
1S30	Ge-Di	=1S28: 250V	=34a	Njr	—
1S300	Z-Di	=1S262: 120V	32a		—
1S3006(A)	Z-Di	6,8V, 1W, 10%, (A=5%)	31a	Tix	BZW22/.., BZX61/.., ZPY.., 1N5921..56,++
1S3007(A)	Z-Di	=1S3006(A): 7,5V	31a		—
1S3008(A)	Z-Di	=1S3006(A): 8,2V	31a		—
1S3009(A)	Z-Di	=1S3006(A): 9,1V	31a		—
1S301	Z-Di	=1S262: 130V	32a		—
1S3010(A)	Z-Di	=1S3006(A): 10V	31a		—
1S3011(A)	Z-Di	=1S3006(A): 11V	31a		—
1S3012(A)	Z-Di	=1S3006(A): 12V	31a		—
1S3013(A)	Z-Di	=1S3006(A): 13V	31a		—
1S3015(A)	Z-Di	=1S3006(A): 15V	31a		—
1S3016(A)	Z-Di	=1S3006(A): 16V	31a		—
1S3018(A)	Z-Di	=1S3006(A): 18V	31a		—
1S302	Z-Di	=1S262: 140V	32a		—
1S3020(A)	Z-Di	=1S3006(A): 20V	31a		—
1S3022(A)	Z-Di	=1S3006(A): 22V	31a		—
1S3024(A)	Z-Di	=1S3006(A): 24V	31a		—
1S3027(A)	Z-Di	=1S3006(A): 27V	31a		—
1S303	Z-Di	=1S262: 150V	32a		—
1S3030(A)	Z-Di	=1S3006(A): 30V	31a		—
1S3033(A)	Z-Di	=1S3006(A): 33V	31a		—
1S3036(A)	Z-Di	=1S3006(A): 36V	31a		—
1S3039(A)	Z-Di	=1S3006(A): 39V	31a		—
1S304	Ref-Di	8..9V, 0,2W	31	Nec	—
1S3043(A)	Z-Di	=1S3006(A): 43V	31a		—
1S3047(A)	Z-Di	=1S3006(A): 47V	31a		—
1S305	Ref-Di	8..9V, 0,2W	31	Nec	—
1S3051(A)	Z-Di	=1S3006(A): 51V	31a		—
1S3056(A)	Z-Di	=1S3006(A): 56V	31a		—
1S306(-M)	Si-Di	SS, 35V, 0,06A, <3ns	31a	Nec	BA218, BAX13, BAY71, 1N4148..49,++
1S3062(A)	Z-Di	=1S3006(A): 62V	31a		—
1S3068(A)	Z-Di	=1S3006(A): 86V	31a		—
1S307	Ge-Di	S, 20V, 0,085A, <100ns	31a	Nec	AAY27, AAZ18
1S3075(A)	Z-Di	=1S3006(A): 75V	31a		—
1S306	Ge-Di	Gl, Uni, 80V, 0,2A	34	Hit	—
1S3082(A)	Z-Di	=1S3006(A): 62V	31a		—
1S309	Ge-Di	Gl, Uni, 120V, 0,25A	34	Hit	—
1S3091(A)	Z-Di	=1S3006(A): 91V	31a		—
1S31	Ge-Di	=1S28: 300V	=34a	Njr	—
1S310(H)	Si-Di	Gl, Uni, 50V, 0,5A	31a	Hit	BY126..127, BY133..135, 1N4001..07,++
1S3100(A)	Z-Di	=1S3006(A): 100V	31a		—
1S311(H,N)	Si-Di	=1S310: 100V	31a		BY126..127, BY133..135, 1N4002..07,++
1S3110(A)	Z-Di	=1S3006(A): 110V	31a		—
1S312(A,H)	Si-Di	=1S310: 200V	31a		BY126..127, BY133..134, 1N4003..07,++
1S3120(A)	Z-Di	=1S3006(A): 120V	31a		—
1S313(H)	Si-Di	=1S310: 300V	31a		BY126..127, BY133..134, 1N4004..07,++

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1S3130(A)	Z-Di	=1S3006(A): 130V	31a		—
1S314(H,N)	Si-Di	=1S310: 400V	31a		BY126..127, BY133..134, 1N4004..07,++
1S315(H)	Si-Di	=1S310: 500V	31a		BY126..127, BY133..134, 1N4005..07,++
1S3150(A)	Z-Di	=1S3006(A): 150V	31a		—
1S316	Si-Di	=1S310: 800V	31a		BY127, BY133, BY227, 1N4006..07,++
1S3160(A)	Z-Di	=1S3006(A): 160V	31a		—
1S317	Si-Di	=1S310: 1000V	31a		BY127, BY133, BY227, 1N4007,++
1S318	Ge-Di	Uni, 75V, 0,05A	31a	Gie	AA117..118, AA132..133, 1N634..635
1S3180(A)	Z-Di	=1S3006(A): 180V	31a		—
1S319	Ge-Di	Uni, 60V, 0,04A	31a	Gie	AA117..118, AA132..134, 1N34, 1N54,++
1S32	Ge-Di	Uni, 75V, 30mA	31a	Tos	AA117..118, AA132..133, 1N634
1S320	Ge-Di	Dem, 40V, 0,05A	31a	Gie	AA113, AA119, 1N34, 1N54, 1N60
1S3200(A)	Z-Di	=1S3006(A): 200V	31a		—
1S321	Ge-Di	Uni, 120V, 0,05A	31a	Gie	AA133, 1N635
1S322	Ge-Di	Uni, 75V, 0,04A	31a	Gie	AA117..118, AA132..133, 1N634..635
1S323	Ge-Di	Uni, 50V, 0,05A	31a	Gie	AA117..118, AA132..134, 1N34, 1N54,++
1S324	Si-Di	SS, 40V, 0,04A	31a	Tos	BA218, BAX13, BAX91, 1N4148..49,++
1S325	Si-Di	SS, 40V, 0,04A	31a	Tos	BA218, BAX13, BAX91, 1N4148..49,++
1S326	Si-Di	Gl, Uni, 200V, 0,5A	34a	Njr	BY126..127, BY133..134, 1N4003..07,++
1S327	Si-Di	=1S326: 400V	34a		BY126..127, BY133..134, 1N4004..07,++
1S328	Si-Di	=1S326: 600V, 0,4A	34a		BY126..1+F887927, BY133..134, 1N4005..07,++
1S329	Si-Di	=1S326: 800V, 0,4A	34a		BY127, BY133, BY227, 1N4006..07,++
1S33	Ge-Di	Uni, 120V, 30mA	31a	Tos	AA132..133, 1N634
1S330	Z-Di	4,4..5,6V, 0,25W	31a	Njr	BZX55/.., BZX79/.., ZPD.., 1N5230..50,++
1S331	Z-Di	=1S330: 5,4..6,6V	31a		—
1S332	Z-Di	=1S330: 6,4..7,6V	31a		—
1S333	Z-Di	=1S330: 7,4..6,6V	31a		—
1S334	Z-Di	=1S330: 8,4..9,6V	31a		—
1S335	Z-Di	=1S330: 9,4..10,6V	31a		—
1S336	Z-Di	=1S330: 10,4..11,6V	31a		—
1S337	Z-Di	=1S330: 11,4..12,6V	31a		—
1S338	Z-Di	=1S330: 12,4..16,1V	31a		—
1S339	Z-Di	=1S330: 15,9..20V	31a		—
1S34	Ge-Di	Uni, 75V, 30mA	31a	Tos	AA117..118, AA132..133, 1N634
1S340	Z-Di	4,4..5,6V, 1,5W	~34a	Njr	BZV47/.., BZY97/.., ZY.., 1N5917..32,++
1S341	Z-Di	=1S340: 5,4..6,6V	~34a		—
1S342	Z-Di	=1S340: 6,4..7,6V	~34a		—
1S343	Z-Di	=1S340: 7,4..8,6V	~34a		—
1S344	Z-Di	=1S340: 8,4..9,6V	~34a		—
1S345	Z-Di	=1S340: 9,4..10,6V	~34a		—
1S346	Z-Di	=1S340: 10,4..11,6V	~34a		—
1S347	Z-Di	=1S340: 11,4..12,6V	~34a		—
1S348	Z-Di	=1S340: 12,4..16,1V	~34a		—
1S349	Z-Di	=1S340: 15,9..20V	~34a		—
1S35	Ge-Di	4x Di, Ringmodulator, 30V, 0,12A		Tos	—
1S350	Ge-Di	Dem, 30V, 15mA	31a	Njr	AA113, AA119, 1N34, 1N54, 1N60
1S351(M,S)	C-Di	AFC	31a	Njr	BA124..125, BB119, 1S2790, 1SV50,++
1S352(M,N)	C-Di	AFC	31a	Njr	BA124..125, BB119, 1S2790, 1SV50,++
1S353(M)	C-Di	AFC	31a	Njr	BA124..125, BB119, 1S2790, 1SV50,++
1S354	Ge-Di	Uni, 75V, 0,04A	31a	Njr	AA117..118, AA132..133, 1N634..635
1S355	Ge-Di	Dem, 30V, 0,05A	31a	Njr	AA113, AA119, 1N34, 1N54, 1N60,++
1S356	Ge-Di	Dem, Uni, 50V, 0,06A	31a	Njr	AA113, AA117..118, 1N34, 1N60,++
1S357	Ge-Di	Dem, 45V	31a	Njr	AA113, AA119, 1N34, 1N54, 1N60,++
1S358	Si-Di	150V, 0,1A	31a	Njr	BA147/150, BA189..190, 1N5606..07,++
1S358-S	Si-Di	=1S358: 50V	31a		BA147/50, BA187..190, 1N5606..09,++
1S359	Si-Di	Gl, Uni, 400V, 0,5A	31a	Nec	BY126..127, BY133..134, 1N4004..07,++
1S36	Si-Di	Gl, Uni, 200V, 0,5A	~34a	Mat	BY126..127, BY133..134, 1N4003..07,++
1S360	Si-Di	UHF-Varaktor, 30GHz	Koax	Nec	—
1S361	Si-Di	UHF-Varaktor, 50GHz	Koax	Nec	—
1S362	Si-Di	UHF-Varaktor, 70GHz	Koax	Nec	—
1S363	Si-Di	UHF-Varaktor, 90GHz	Koax	Nec	—
1S364	Ge-Di	AFC	4	Njr	—
1S365	Ge-Di	AFC	4	Njr	—
1S366	Ge-Di	AFC	4	Njr	—
1S367	Si-Di	Gl, Uni, 100V, 0,4A	34a	Njr	BY126..127, BY133..135, 1N4002..07,++
1S368	Si-Di	=1S367: 200V	34a		BY126..127, BY133..134, 1N4003..07,++

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1S369	Si-Di	=1S367: 300V	34a		BY126..127, BY133..134, 1N4004..07,++
1S37	Si-Di	=1S36: 400V	≈34a		BY126..127, BY133..134, 1N4004..07,++
1S370	Si-Di	=1S367: 400V	34a		BY126..127, BY133..134, 1N4004..07,++
1S371	Si-Di	=1S367: 500V	34a		BY126..127, BY133..134, 1N4005..07,++
1S372	Si-Di	=1S367: 600V	34a		BY126..127, BY133..134, 1N4005..07,++
1S373	Si-Di	Gl, Uni, 100V, 0,3A	34	Inr	BY126..127, BY133..135, 1N4002..07,++
1S374	Si-Di	=1S373: 200V	34		BY126..127, BY133..134, 1N4003..07,++
1S375	Si-Di	=1S373: 400V	34		BY126..127, BY133..134, 1N4004..07,++
1S376	Si-Di	=1S373: 500V	34		BY126..127, BY133..134, 1N4005..07,++
1S377	Si-Di	=1S373: 600V	34		BY126..127, BY133..134, 1N4005..07,++
1S378	Si-Di	Gl, Uni, 100V, 0,3A	34	Inr	BY126..127, BY133..135, 1N4002..07,++
1S379	Si-Di	=1S378: 200V	34		BY126..127, BY133..134, 1N4003..07,++
1S36	Si-Di	≈1S36: 700V	≈34a		BY127, BY133, BY227, 1N4006..07,++
1S380	Si-Di	≈1S378: 400V	34		BY126..127, BY133..134, 1N4004..07,++
1S361	Si-Di	=1S376: 500V	34		BY126..127, BY133..134, 1N4005..07,++
1S362	Si-Di	=1S378: 600V	34		BY126..127, BY133..134, 1N4005..07,++
1S363	Si-Di	Gl-L, 100V, 0,8A	32a	Inr	(BY126..127, BY133..135, 1N4002..07++)
1S364	Si-Di	=1S383: 200V	32a		(BY126..127, BY133..134, 1N4003..07++)
1S365	Si-Di	=1S383: 400V	32a		(BY126..127, BY133..134, 1N4004..07++)
1S386	Si-Di	≈1S383: 500V	32a		(BY126..127, BY133..134, 1N4005..07++)
1S367	Si-Di	=1S363: 600V	32a		(BY126..127, BY133..134, 1N4005..07++)
1S386	Si-Di	Gl-L, 100V, 0,8A	32a	Inr	(BY126..127, BY133..135, 1N4002..07++)
1S369	Si-Di	=1S386: 200V	32a		(BY126..127, BY133..134, 1N4003..07++)
1S39	Si-Di	=1S36: 600V, 0,4A	≈34a		BY127, BY133, BY227, 1N4006..07,++
1S390	Si-Di	=1S386: 400V	32a		(BY126..127, BY133..134, 1N4004..07++)
1S391	Si-Di	≈1S388: 500V	32a		(BY126..127, BY133..134, 1N4005..07++)
1S392	Si-Di	=1S386: 600V	32a		(BY126..127, BY133..134, 1N4005..07++)
1S393	Si-Di	Gl, Uni, 400V, 0,3A	≈31a	Inr	BA157..159, BY204/4, BY206..207,++
1S394	Si-Di	=1S393: 0,4A	≈31a		BA157..159, BY204/4, BY206..207,++
1S395	Si-Di	Gl, Uni, 400V, 0,5A	31a	Inr	BY126..127, BY133..134, 1N4004..07,++
1S396	Si-Di	=1S395: 600V	31a		BY126..127, BY133..134, 1N4005..07,++
1S397	Si-Di	=1S395: 600V	31a		BY127, BY133, BY227, 1N4006..07,++
1S396	Si-Di	≈1S395: 1000V	31a		BY127, BY133, BY227, 1N4007,++
1S399[IR]	Si-Di	Gl, Uni, 400V, 0,8A	34	Inr	BY126..127, BY133..134, 1N4004..07,++
1S40	Si-Di	Gl, Uni, 100V, 0,75A	34a	Fui	BY126..127, BY133..135, 1N4002..07,++
1S4006..4200(A)	Z-Di	≈1S3006..3200(A): 1,5W	34a	Tix	BZV47/.., BZY97/.., ZY.., 1N5921..56,++
1S400[IR]	Si-Di	=1S399[IR]: 600V	34		BY126..1+F890627, BY133..134, 1N4005..07,++
13401(R)[Texas]	Si-Di	=1S420(R)[Texas]		Tix	→1S420(R)[Texas[
1S401[IR]	Si-Di	=1S399[IR]: 600V	34		BY127, BY133, BY227, 1N4006..07,++
1S402(R)[Texas]	Si-Di	=1S421(R)[Texas]		Tix	→1S421(R)[Texas]
1S402[IR]	Si-Di	=1S399[IR]: 1000V	34		BY127, BY133, BY227, 1N4007,++
13403(R)[Texas]	Si-Di	≈1S422(R)[Texas]		Tix	→1S422(R)[Texas]
1S403[IR]	Si-Di	=1S369[IR]: 1200V	34		BY127, BY133, BY227, GP10Q,++
1S404(R)[Texas]	Si-Di	=1S423(R)[Texas]		Tix	→1S423(R)[Texas]
1S404[IR]	Si-Di	Gl, Uni, 600V, 0,1A	31a	Inr	BA157..159, BAY89..91, BY203/12,++
1S405(R)[Texas]	Si-Di	=1S424(R)[Texas]		Tix	→1S424(R)[Texas]
1S405[IR]	Si-Di	=1S404[IR]: 600V	31a		BA159, BAY90..91, BY203/12,++
1S406(R)[Texas]	Si-Di	=1S425(R)[Texas]		Tix	→1S425(R)[Texas]
1S406[IR]	Si-Di	=1S404[IR]: 1000V	31a		BA159, BAY90..91, BY203/12,++
1S407(R)[Texas]	Si-Di	=1S426(R)[Texas]		Tix	→1S426(R)[Texas]
1S407[IR]	Si-Di	=1S404[IR]: 1200V	31a		BAY91, BY203/12, BY584, SHG1,5,++
1S408(R)[Texas]	Si-Di	=1S427(R)[Texas]		Tix	→1S427(R)[Texas]
1S408[IR]	Si-Di	kV-Gl, 1,5kV, 0,38A	31a	Inr	1N1732A
1S409[IR]	Si-Di	=1S408[IR]: 1,8kV	31a		1N1732A
1S41	Si-Di	≈1S40: 200V	34a		BY126..127, BY133..134, 1N4003..07,++
1S410R..19R[Texas]	Si-Di	=1S410..419[Texas]	32b		BYX38/..R, BYX39/..R
1S410[IR]	Si-Di	=1S408[IR]: 2,4kV	31a		1N1733A
1S410[Texas]	Si-Di	Gl-L, 100V, 3A(Tc=125°)	32a	Tix	BYX38/300, BYX39/600
1S411[IR]	Si-Di	=1S408[IR]: 3,6kV, 0,36A	31a		1N1734A
1S411[Texas]	Si-Di	≈1S410[Texas]: 200V	32a		BYX38/300, BYX39/600
1S412[IR]	Si-Di	=1S408[IR]: 4,8kV, 0,36A	31a		1N1734A
1S413[IR]	Si-Di	=1S408[IR]: 6kV, 0,36A	31a		—
1S413[Texas]	Si-Di	=1S410[Texas]: 400V	32a		BYX38/600, BYX39/600
1S414[IR]	Si-Di	≈1S408[IR]: 7,2kV, 0,33A	31a		—
1S415[IR]	Si-Di	=1S408[IR]: 12kV, 0,25A	31a		—
1S415[Texas]	Si-Di	≈1S410[Texas]: 600V	32a		BYX38/600, BYX39/600

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1S416[IR]	Si-Di	=1S408[IR]: 16kV, 0,25A	31a		—
1S417[IR]	Si-Di	Gl-L, 50V, 3A(Tc=70°)	32a	Inr	BYX38/300, BYX39/600
1S417[Texes]	Si-Di	=1S410[Texas]. 800V	32a		BYX38/900, BYX39/800
1S418[IR]	Si-Di	=1S417[IR]: 100V	32a		BYX38/300, BYX39/600
1S419[IR]	Si-Di	=1S417[IR]: 150V	32a		BYX38/300, BYX39/800
1S419[Texas]	Si-Di	=1S410[Texas]: 1000V	32a		BYX38/1200, BYX39/1000
1S42	Si-Di	=1S40: 300V	34a		BY126..127, BY133..134, 1N4004..07,++
1S420R..27R[Texas]	Si-Di	=1S420[Texas]: 800V	32b		BYW88/..R, BYX86R..81R
1S420[IR]	Si-Di	=1S417[IR]: 200V	32a		BYX38/300, BYX39/600
1S420[Texas]	Si-Di	Gl-L, 100V, 10A(Tc=100°)	32a	Tix	BYW88/100, BYX76..81, 1N4506..11,++
1S421[IR]	Si-Di	=1S417[IR]: 250V	32a		BYX38/300, BYX39/600
1S421[Texes]	Si-Di	=1S420[Texas]: 200V	32a		BYW88/200, BYX77..81, 1N4506..11,++
1S422[IR]	Si-Di	=1S417[IR]: 300V	32a		BYX38/300, BYX39/600
1S423[IR]	Si-Di	=1S417[IR]: 400V	32a		BYX38/600, BYX39/600
1S423[Texas]	Si-Di	=1S420[Texas]: 400V	32a		BYW88/400, BYX78..81, 1N4507..11,++
1S424[IR]	Si-Di	=1S417[IR]: 500V	32a		BYX38/600, BYX39/600
1S425[IR]	Si-Di	=1S417[IR]: 600V	32a		BYX38/600, BYX39/600
1S425[Texas]	Si-Di	=1S420[Texas]: 800V	32a		BYW88/600, BYX79..81, 1N4506..11,++
1S426(G)[Japan	Ge-Di	Dem, 15..25V, 20..50mA	31a	Say	AA112..114, 1N34, 1N54, 1N60,++
1S427[Japan]	Z-Di	13,5..15V, 0,3W	31a	Tos	BZX55/C15, BZX79/C15, ZPD15, 1N5244
1S427[Texas]	Si-Di	=1S420[Texas]: 800V	32a		BTW88/600, BYX80..81, 1N4509..11,++
1S43	Si-Di	=1S40: 400V	34a		BY126..127, BY133..134, 1N4004..07,++
1S431	Si-Di	Gl-L, 100V, 100A(Tc=105°)	73a	Nec	1N3288..97
1S432	Si-Di	=1S431: 200V	73a		1N3289..97
1S433	Si-Di	=1S431: 300V	73a		1N3290..97
1S434	Si-Di	=1S431: 400V	73a		1N3291..97
1S435	Si-Di	=1S431: 500V	73a		1N3292..97
1S436	Si-Di	=1S431: 800V	73a		1N3293..97
1S437	Si-Di	=1S431: 700V	73a		1N3294..97
1S438	Si-Di	=1S431: 800V	73a		1N3294..97
1S439	Si-Di	=1S431: 900V	73a		1N3295..97
1S44	Si-Di	=1S40: 500V	34a		BY126..127, BY133..134, 1N4005..07,++
1S440	Si-Di	=1S431: 1000V	73a		1N3295..97
1S441	Ge-Di	Dem, Uni, 45V, 30mA	31a	Fui	AA113, AA119, 1N34, 1N54, 1N60
1S442	Ge-Di	Dem, Uni, 43V, 0,1A	31a	Fui	AA113, AA119, 1N34, 1N54, 1N60
1S443	Ge-Di	S, 43V, 0,12A, <2µs	31a	Fui	AA136, AAY49, AAZ15, AAZ17
1S444	Ge-Di	S, 30V, 0,09A, <200ns	31a	Fui	AAY..49, AAZ15, AAZ17
1S445	Ge-Di	S, 65V, 0,1A, <450ns	31a	Fui	AAZ15, AAZ17
1S446	Ge-Di	Dem, Uni, 60V, 30mA	31a	Fui	AA113, 1N34, 1N54, 1N60
1S447	Ge-Di	Dem, Uni, 75V, 40mA	31a	Fui	AA117..118, AA132..133
1S448	Ge-Di	Dem, Uni, 110V, 40mA	31a	Fui	AA117..118, AA132..133
1S449	Ge-Di	Dem, Uni, 110V, 40mA	31a	Fui	AA117..118, AA132..133
1S44[Texas]	Si-Di	SS, 40V, 0,1A, <8ns	31a	Fch, Tix	BA318, BAY38, 1N4148..49, 1N4151,++
1S45	Si-Di	=1S40: 800V	34a		BY126..127, BY133..134, 1N4005..07,++
1S450	Ge-Di	Uni, 140V, 30mA	≈2c	Fui	AA133
1S451	Ge-Di	Dem, Uni, 60V, 40mA	31a	Fui	AA113, 1N43, 1N54, 1N60
1S452	Ge-Di	Dem, Uni, 75V, 40mA	31a	Fui	AA117..118, AA132..133
1S453	Ge-Di	Dem, Uni, 75V, 40mA	31a	Fui	AA117..118, AA132..133
1S454	Ge-Di	Dem, Uni, 45V, 40mA	31a	Fui	AA113, AA119, 1N34, 1N54, 1N60
1S455	Ge-Di	Dem, Uni, 35V, 40mA	31a	Fui	AA113, AA119, 1N34, 1N54, 1N60
1S456	Si-Di	Gl, Uni, 40V, 0,1A	31a	Fui	BA147/50, BA187..190, 1N5606..09,++
1S457	Si-Di	=1S456: 80V	31a		BA147/100, BA188..190, 1N5606..F898709,++
1S458	Si-Di	=1S456: 150V	31a		BA147/150, BA189..190, 1N5606..07,++
1S459	Si-Di	=1S456: 200V	31a		BA147/230, BA190, 1N5606..07,++
1S46	Si-Di	=1S40: 700V	34a		BY127, BY133, BY227, 1N4006..07,++
1S460	Si-Di	SS, 22V, 0,045A, <3ns	31a	Fui	BA317, BAY71, BAY94, 1N4148..49,++
1S461	Si-Di	SS, 90V, 0,15A, <3ns	31a	Fui	BA219, 1N4148..49, 1N4446..49,++
1S462	Si-Di	SS, 90V, 0,22A, <3ns	31a	Fui	1N4146..49, 1N4151, 1N4446..49,++
1S463	Si-Di	S, 125V, 0,9A, <30ns	34	Fui	EGP10C, FE1C
1S464	Si-St	0,76..0,64V(10mA)	31a	Fui, Nec	BA220, BZ102/0V7, BZX55/C0V8, ZPD1
1S465	Si-Di	SS, 43V, 0,045A, <10ns	31a	Fui	BA218, BAX13, BAX91, 1N4148..49,++
1S466	Si-Di	SS, 43V, 0,045A, <1ns	31a	Fui	—
1S467	Si-St	Stabi, SS, 0,84..0,7V(3mA), <6ns	31a	Fui, Nec	BA220, BA315
1S468	Si-Di	SS, 40V, 0,115A, <3ns	31a	Fui	BA318, BAY36, 1N4148..49, 1N4151,++
1S47	Si-Di	=1S40: 800V	34a		BY127, BY133, BY227, 1N4006..07,++
1S470[H,L,M]	Z-Di	5,5..6,5V, 0,25W	31a	Fui	BZX55/.., BZX79/.., ZPD.., 1N5233..62,++

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1S471(H,L,M)	Z-Di	=1S470: 6,5..8V	31a		—
1S472(H,L,M)	Z-Di	=1S470: 8..10V	31a		—
1S473(H,L,M)	Z-Di	=1S470: 10..12,5V	31a		—
1S474(H,L,M)	Z-Di	=1S470: 12,5..16V	31a		—
1S475(H,L,M)	Z-Di	=1S470: 16..20V	31a		—
1S476(H,L,M)	Z-Di	=1S470: 20..25V	31a		—
1S477(H,L,M)	Z-Di	=1S470: 25..31V	31a		—
1S476(H,L,M)	Z-Di	=1S470: 31..41V	31a		—
1S479(H,L,M)	Z-Di	=1S470: 41..C919851V	31a		—
1S48	Si-Di	FM/VHF-AFC	31a	Tos	BA111, BA124, 1S2790, 1SV50, ++
1S480(H,L,M)	Z-Di	5,5..6,5V, 1W	34	Fui	BZW22/.., BZX61/.., ZPY.., 1N5919..41, ++
1S481(H,L,M)	Z-Di	=1S480: 6,5..8V	34		—
1S482(H,L,M)	Z-Di	=1S480: 8..10V	34		—
1S483(H,L,M)	Z-Di	=1S480: 10..12,5V	34		—
1S484(H,L,M)	Z-Di	=1S480: 12,5..16V	34		—
13485(H,L,M)	Z-Di	=1S480: 16..20V	34		—
1S466(H,L,M)	Z-Di	=1S480: 20..25V	34		—
1S487(H,L,M)	Z-Di	=1S480: 25..31V	34		—
1S488(H,L,M)	Z-Di	=1S480: 31..41V	34		—
1S489(H,L,M)	Z-Di	=1S480: 41..51V	34		—
1S49	Si-Di	FM/VHF-AFC	31a	Tos	BA111, BA124, 1S2790, 1SV50, ++
1S490(H,L,M)	Z-Di	5,5..6,5V, 3W	32a	Fui	BZX98/.., BZY93/.., ZX.., 1N2970..97, ++
1S491(H,L,M)	Z-Di	=1S490: 8,5..8V	32a		—
1S492(H,L,M)	Z-Di	=1S490: 8..10V	32a		—
1S493(H,L,M)	Z-Di	=1S490: 10..12,5V	32a		—
1S494(H,L,M)	Z-Di	=1S490: 12,5..16V	32a		—
1S495(H,L,M)	Z-Di	=1S490: 16..20V	32a		—
1S496(H,L,M)	Z-Di	=1S490: 20..25V	32a		—
1S497(H,L,M)	Z-Di	=1S490: 25..31V	32a		—
1S498(H,L,M)	Z-Di	=1S490: 31..41V	32a		—
1S499(H,L,M)	Z-Di	=1S490: 41..51V	32a		—
1S50	Ge-Di	Dem, 40V, 50mA	31a	Tos	AA113, AA119, 1N34, 1N54, 1N60, ++
1S500	Si-Di	SS, 43V, 0,045A, <3ns	31a	Fui	BA218, BAX13, BAX91, 1N4148..49, ++
1S501	Si-Di	SS, 43V, 0,075A, <3ns	31a	Fui	BA218, BAX13, BAX91, 1N4148..49, ++
1S5015(A)	Z-Di	15V, 10W(Tc=100°), 10%, (A=5%)	32b	Tix	BZX98/.., BZY93/.., ZX.., 1N2979..3011
1S5015C...5150C	Z-Di	=1S5015..5150(A): bidirektional	32		—
1S5015R..5150R	Z-Di	=1S5015..5150(A):	32a		—
1S5016(A)	Z-Di	=1S5015(A): 16V	32b		—
1S5018(A)	Z-Di	=1S5015(A): 18V	32b		—
1S501M	Si-Di	=1S501: 22V, 0,045A, <1ns	31a		—
1S502...541	Ge-Di		31	Fui	—
1S5020(A)	Z-Di	=1S5015(A): 20V	32b		—
1S5022(A)	Z-Di	=1S5015(A): 22V	32b		—
1S5024(A)	Z-Di	=1S5015(A): 24V	32b		—
1S5027(A)	Z-Di	=1S5015(A): 27V	32b		—
1S5030(A)	Z-Di	=1S5015(A): 30V	32b		—
1S5033(A)	Z-Di	=1S5015(A): 33V	32b		—
1S5036(A)	Z-Di	=1S5015(A): 36V	32b		—
1S5039(A)	Z-Di	=1S5015(A): 39V	32b		—
1S5043(A)	Z-Di	=1S5015(A): 43V	32b		—
1S5047(A)	Z-Di	=1S5015(A): 47V	32b		—
1S5051(A)	Z-Di	=1S5015(A): 51V	32b		—
1S5056(A)	Z-Di	=1S5015(A): 56V	32b		—
1S5062(A)	Z-Di	=1S5015(A): 62V	32b		—
1S5068(A)	Z-Di	=1S5015(A): 68V	32b		—
1S5075(A)	Z-Di	=1S5015(A): 75V	32b		—
1S5082(A)	Z-Di	=1S5015(A): 62V	32b		—
1S5091(A)	Z-Di	=1S5015(A): 91V	32b		—
1S51	Z-Di	3,8..4,5V	~34a	Tos	BZW22/.., BZX61/.., ZPY.., 1N5915..25, ++
1S5100(A)	Z-Di	=1S5015(A): 100V	32b		—
1S5110(A)	Z-Di	=1S5015(A): 110V	32b		—
1S5120(A)	Z-Di	=1S5015(A): 120V	32b		—
1S5130(A)	Z-Di	=1S5015(A): 130V	32b		—
1S5150(A)	Z-Di	=1S5015(A): 150V	32b		—
1S52	Z-Di	5,2..6,2V	~34a		—
1S53	Z-Di	6,0..7,1V	~34a		—

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1S54	Z-Di	6,9..6,1V	~34a		—
1S542	Si-Di	Gl, Uni, 500V, 0,5A	31a	Tos	BY126..127, BY133..134, 1N4005..07,++
1S543	Si-Di	UHF-M, 720MHz		Hit	—
1S544	Si-Di	Gl-L, 800V, 10A(Tc=120°)	32a	Nec	BYX42/900, BYX98/900
1S545	Si-Di	=1S544: 1000V	32a		BYX42/1200, BYX98/1200
1S546	Si-Di	Gl-L, 800V, 20A(Tc=120°)	32a	Nec	1N4528..30
1S547	Si-Di	=1S546: 1000V	32a		1N4528..30
1S548	Si-Di	SS, UHF, 100V, 0,1A, 9GHz, <4ns	Koax	Oki	—
1S55	Z-Di	7,9..9,1V	~34a		—
1S550	Ref-Di	8..9V	2c	Nec	BZX51, 1N4780
1S551	Ref-Di	8..9V	2c		BZX52, 1N4781
1S552	Ref-Di	8..9V	2c		BZX53, 1N4782
1S553(T)	C-Di	FM-AFC	31a	Say	BA111, BA124, 1S2790, 1SV50,++
1S554(T)	C-Di	FM-AFC	31a	Say	BA111, BA124, 1S2790, 1SV50,++
1S555	C-Di	FM-AFC	31a	Say	BA111, BA124, 1S2790, 1SV50,++
1S556	C-Di	FM-AFC	31a	Say	BA111, BA124, 1S2790, 1SV50,++
1S557	Si-Di	Gl, Uni, 800V, 0,6A	12	Say	BY127, BY133, BY227, 1N4006..07,++
1S557H	Si-Di	=1S557: 1100V	12		BY127, BY133, BY227, GP10Q,++
1S558	Si-Di	=1S557: 500V	12		BY126..127, BY133..134, 1N4005..07,++
1S559	Si-Di	=1S557: 300V	12		BY126..127, BY133..134, 1N4004..07,++
1S56	Z-Di	8,9..10,1V	~34a		—
1S560(H)	Ge-Di	S, 15V, 0,04A, <200ns	31a	Hit	AAY27, 1N631, 1N633, 1N3592
1S581..569(A)	Ge-Di		31a	Njr	—
1S57	Si-Di		~34a	Tos	—
1S58	Ge-Br	4xDi, Br, 75V, 30mA		Tos	—
1S80	Si-Di	Gl, Uni, 50V, 0,75A	34	Son	BY126..127, BY133..135, 1N4001..07,++
1S8006(A)	Z-Di	6,8V, 10W(Tc=100°), 10%, (A=5%)	32b	Tix	BZX98/.., BZY93/.., ZX.., 1N5921..56
1S6006R..6200R	Z-Di	=1S6006: 6200(A)	32a		—
1S6007(A)	Z-Di	=1S6006(A): 7,5V	32b		—
1S6006(A)	Z-Di	=1S6006(A): 8,2V	32b		—
1S6009(A)	Z-Di	=1S6006(A): 9,1V	32b		—
1S6010(A)	Z-Di	=1S6006(A): 10V	32b		—
1S6011(A)	Z-Di	=1S8006(A): 11V	32b		—
1S6012(A)	Z-Di	=1S6006(A:) 12V	32b		—
1S6013(A)	Z-Di	=1S6006(A): 13V	32b		—
1S8015(A)	Z-Di	=1S6006(A): 15V	32b		—
1S6016(A)	Z-Di	=1S6006(A): 16V	32b		—
1S6018(A)	Z-Di	=1S6006(A): 18V	32b		—
1S6020(A)	Z-Di	=1S6006(A): 20V	32b		—
1S6022(A)	Z-Di	=1S8006(A): 22V	32b		—
1S6024(A)	Z-Di	=1S6006(A): 24V	32b		—
1S6027(A)	Z-Di	=1S6006(A): 27V	32b		—
1S6030(A)	Z-Di	=1S6006(A): 30V	32b		—
1S6033(A)	Z-Di	=1S6006(A): 33V	32b		—
1S6036(A)	Z-Di	=1S6006(A): 36V	32b		—
1S6039(A)	Z-Di	=1S6006(A): 39V	32b		—
1S6043(A)	Z-Di	=1S6006(A): 43V	32b		—
1S6047(A)	Z-Di	=1S6006(A): 47V	32b		—
1S6051(A)	Z-Di	=1S6006(A): 51V	32b		—
1S6056(A)	Z-Di	=1S6006(A): 56V	32b		—
1S6062(A)	Z-Di	=1S6006(A): 62V	32b		—
1S6068(A)	Z-Di	=1S6006(A): 68V	32b		—
1S6075(A)	Z-Di	=1S6008(A): 75V	32b		—
1S6062(A)	Z-Di	=1S6006(A): 82V	32b		—
1S8091(A)	Z-Di	=1S6006(A): 91V	32b		—
1S61	Si-Di	=1S60: 100V	34		BY126..127, BY133..135, 1N4001..07,++
1S6100(A)	Z-Di	=1S6006(A): 100V	32b		—
1S611	Z-Di	2..3,2V, 0,2W	2c	Khe	BZX55/.., BZX79/.., ZPD.., 1N5221..37,++
1S6110(A)	Z-Di	=1S6006(A): 110V	32b		—
1S612	Z-Di	=1S611: 3..3,9V	2c		—
1S6120(A)	Z-Di	=1S6006(A): 120V	32b		—
1S613	Z-Di	=1S611: 3,7..4,5V	2c		—
1S6130(A)	Z-Di	=1S6006(A): 130V	32b		—
1S614	Z-Di	=1S611: 4,3..5,4V	2c		—
1S615	Z-Di	=1S611: 5,2..6,4V	2c		—
1S6150(A)	Z-Di	=1S6006(A): 150V	32b		—

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1S616	Z-Di	=1S611: 6,2..8V	2c		—
1S6160(A)	Z-Di	=1S6006(A): 160V	32b		—
1S617	Z-Di	7,5..10V, 0,15W	2c	Khe	BZX55/.., BZX79/.., ZPD.., 1N5236..59,++
1S618	Z-Di	=1S617: 9..12V	2c		—
1S6180(A)	Z-Di	=1S6006(A): 160V	32b		—
1S619	Z-Di	=1S617: 11..14,5V	2c		—
1S62	Si-Di	=1S60: 200V	34		BY126..127, BY133..134, 1N4002..07,++
1S620	Z-Di	=1S617: 13,5..18V	2c		—
1S6200(A)	Z-Di	=1S6006(A): 200V	32b		—
1S621	Z-Di	=1S617: 17..21V	2c		—
1S822	Z-Di	=1S617: 20..27V	2c		—
1S623	Z-Di	=1S617: 25..32V	2c		—
1S624	Z-Di	=1S617: 30..39V	2c		—
1S63	Si-Di	=1S60: 300V	34		BY126..127, BY133..134, 1N4003..07,++
1S632	Z-Di	3..3,9V, 0,2W	2c	Khe	BZX55/.., BZX79/.., ZPD.., 1N5225..37,++
1S633	Z-Di	=1S632: 3,7..4,5V	2c		—
1S634	Z-Di	=1S632: 4,3..5,4V	2c		—
1S635	Z-Di	=1S632: 5,2..6,4V	2c		—
1S636	Z-Di	=1S632: 6,2..8V	2c		—
1S64	Si-Di	=1S60: 400V	34		BY126..127, BY133..134, 1N4004..07,++
1S65	Si-Di	=1S60: 500V	34		BY126..127, BY133..134, 1N4005..07,++
1S66	Si-Di	=1S60: 600V	34		BY126..127, BY133..134, 1N4005..07,++
1S661	Si-Di	Gl, 400V, 1A(Tc=120°)	34	Fjd	BY252..255, BYW17/400, 1N5404..08,++
1S662	Si-Di	=1S661: 600V	34		BY254..255, BYW17/600, 1N5407..08,++
1S663	Si-Di	=1S661: 1000V	34		BY255, BY228, BYW17/1000, 1N5408,++
1S664	Si-Di	=1S661: 1200V	34		BY255, BY228, BYW17/1200
1S665	Si-Di	Gl-L, 400V, 2,5A(Tc=120°)	≈32b	Fjd	BYX38/600R, BYX39/600R
1S666	Si-Di	=1S665: 600V	≈32b		BYX38/900R, BYX39/600R
1S667	Si-Di	=1S665: 1000V	≈32b		BYX38/1200R, BYX39/1000R
1S666	Si-Di	=1S665: 1200V	≈32b		BYX38/1200R, BYX39/1200R
1S669	Si-Di	Gl-L, 400V, 10A(Tc=120°)	73b	Fjd	BYX42/600R, BYX98/600R
1S670	Si-Di	=1S669: 600V	73b		BYX42/900R, BYX98/900R
1S671	Si-Di	=1S669: 1000V	73b		BYX42/1200R, BYX98/1200R
1S672	Si-Di	=1S669: 1200V	73b		BYX42/1200R, BYX98/1200R
1S673	Si-Di	Gl-L, 400V, 20A(Tc=120°)	73b	Fjd	BYX56/600R, BYX97/600R
1S674	Si-Di	=1S673: 800V	73b		BYX56/600R, BYX97/900R
1S675	Si-Di	=1S673: 1000V	73b		BYX56/1000R, BYX97/1200R
1S678	Si-Di	=1S673: 1200V	73b		BYX56/1200R, BYX97/1200R
1S677	Si-Di	Gl-L, 400V, 82,5A(Tc=105°)	73b	Fjd	1N3291R..97R
1S678	Si-Di	=1S677: 600V	73b		1N3294R..97R
1S679	Si-Di	=1S677: 1000V	73b		1N3295R..97R
1S660	Si-Di	=1S677: 1200V	73b		1N3296R..97R
1S681	Si-Di	Gl-L, 400V, 200A(Tc=105°)	73b	Fjd	1N3739R..44R
1S682	Si-Di	=1S661: 800V	73b		1N3741R..44R
1S683	Si-Di	=1S661: 1000V	73b		1N3742R..44R
1S664	Si-Di	=1S661: 1200V	73b		1N3743R..44R
1S665	Si-Di	Gl, 300V, 0,35A	31a	Gie	BA157..159, BY204/4, BY206..207,++
1S666	Si-Di	=1S685: 450V	31a		BA158..159, BY204/8, BY207,++
1S667	Si-Di	=1S685: 750V	31a		BA158..159, BY204/8, BY268..269,++
1S666	Si-Di	=1S665: 1200V	31a		BY127, BY133, BY227, BY268..269,++
1S689(A)	Ge-Di	TV-Damper-Di, 200..270V, 6A(Tc=50°)	22	Hit	—
1S690	Z-Di	3,6..4,3, 1W	34	Inr	BZW22/.., BZX61/.., ZPY.., 1N5914..36,++
1S691	Z-Di	=1S690: 4,3..5,1V	34		—
1S692	Z-Di	=1S690: 5,1..6,2V	34		—
1S693	Z-Di	=1S690: 6,2..7,5V	34		—
1S694	Z-Di	=1S690: 7,5..9,1V	34		—
1S695	Z-Di	=1S690: 9,1..11V	34		—
1S696	Z-Di	=1S690: 11..13V	34		—
1S697	Z-Di	=1S690: 13..16V	34		—
1S698	Z-Di	=1S690: 16..20V	34		—
1S699	Z-Di	=1S690: 20..24V	34		—
1S700	Z-Di	=1S690: 24..30V	34		—
1S700P	Si-Di	TV			(BY329/1000, BY359/1000, BYW19/1000,++)
1S701	Z-Di	3,6..4,3V, 3,5W	32	Inr	BZX98/.., BZY93/.., ZX.., 1N2970..69,++
1S702	Z-Di	=1S701: 4,3..5,1V	32		—
1S703	Z-Di	=1S701: 5,1..6,2V	32		—

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1S7030(A,B)	Z-Di	3V, 0,4W, 10%, (A=5%, B=15%)	31a	Tix	BZX55/.., BZX83/.., ZPD.., 1N5225..46,++
1S7033(A,B)	Z-Di	=1S7030(A,B): 3,3V	31a		—
1S7036(A,B)	Z-Di	=1S7030(A,B): 3,6V	31a		—
1S7039(A,B)	Z-Di	=1S7030(A,B): 3,9V	31a		—
1S704	Z-Di	=1S701: 6,2..7,5V	32		—
1S7043(A,B)	Z-Di	=1S7030(A,B): 4,3V	31a		—
1S7047(A,B)	Z-Di	=1S7030(A,B): 4,7V	31a		—
1S705	Z-Di	=1S701: 7,5..9,1V	32		—
1S7051(A,B)	Z-Di	=1S7030(A,B): 5,1V	31a		—
1S7056(A,B)	Z-Di	=1S7030(A,B): 5,6V	31a		—
1S706	Z-Di	=1S701: 9,1..11V	32		—
1S7062(A,B)	Z-Di	=1S7030(A,B): 6,2V	31a		—
1S7063(A,B)	Z-Di	=1S7030(A,B): 6,6V	31a		—
1S707	Z-Di	=1S701: 11..13V	32		—
1S7075(A,B)	Z-Di	=1S7030(A,B): 7,5V	31a		—
1S706	Z-Di	=1S701: 13..16V	32		—
1S7082(A,B)	Z-Di	=1S7030(A,B): 8,2V	31a		—
1S709	Z-Di	=1S701: 16..20V	32		—
1S7091(A,B)	Z-Di	=1S7030(A,B): 9,1V	31a		—
1S71	Si-Di	Uni, 175V, 0,06A	31a	Tos	BA147/230, BA190, 1N5195..96,++
1S710	Z-Di	=1S701: 20..24V	32		—
1S7100(A,B)	Z-Di	=1S7030(A,B): 10V	31a		—
1S711	Z-Di	=1S701: 24..30V	32		—
1S7110(A,B)	Z-Di	=1S7030(A,B): 11V	31a		—
1S712	Z-Di	3,6..4,3V, 10W	32	Inr	BZX98/.., BZY93/.., ZX.., 1N2970..89,++
1S7120(A,B)	Z-Di	=1S7030(A,B): 12V	31a		—
1S713	Z-Di	=1S712: 4,3..5,1V	32		—
1S7130(A,B)	Z-Di	=1S7030(A,B): 13V	31a		—
1S714	Z-Di	=1S712: 5,1..6,2V	32		—
1S715	Z-Di	=1S712: 6,2..7,5V	32		—
1S7150(A,B)	Z-Di	=1S7030(A,B): 15V	31a		—
1S716	Z-Di	=1S712: 7,5..9,1V	32		—
1S7160(A,B)	Z-Di	=1S7030(A,B): 16V	31a		—
1S717	Z-Di	=1S712: 9,1..11V	32		—
1S718	Z-Di	=1S712: 11..13V	32		—
1S719	Z-Di	=1S712: 13..16V	32		—
1S72	Si-Di	=1S71: 130V	31a	Tos	BA147/150, BA189..190, 1N5195..96,++
1S720	Z-Di	=1S712: 16..20V	32		—
1S721	Z-Di	=1S712: 20..24V	32		—
1S722	Z-Di	=1S712: 24..30V	32		—
1S723	Si-Di	GI-L, 400V, 6A(Tc=105°)	32	Inr	BYX38/600, BYX39/600
1S724	Si-Di	=1S723: 600V	32		BYX38/600, BYX39/600
1S725	Si-Di	=1S723: 800V	32		BYX38/900, BYX39/600
1S726	Si-Di	=1S723: 1000V	32		BYX38/1200, BYX39/1000
1S73(A)	Ge-Di	S, 20..30V, 0,12A, <900ns	31a	Tos	AAY+F932849, AAZ15, AAZ17
1S731	Si-Di	SS, 50V, 0,1A, <4ns	31a	Nec	BA318, BAY38, 1N4148..49, 1N4151,++
1S732	Si-Di	GI-L, 200V, 250A(Tc=105°)	73a	Nec	1N3738..44
1S733	Si-Di	=1S732: 300V	73a		1N3737..44
1S734	Si-Di	=1S732: 400V	73a		1N3738..44
1S735	Si-Di	=1S732: 500V	73a		1N3739..44
1S736	Si-Di	=1S732: 600V	73a		1N3740..44
1S737	Si-Di	=1S732: 700V	73a		1N3741..44
1S738	Si-Di	=1S732: 600V	73a		1N3741..44
1S739	Si-Di	=1S732: 900V	73a		1N3742..44
1S74	Ge-Di	Uni, 75V, 50mA	31a	Njr,Son	AA117..118, AA132..133
1S740	Si-Di	=1S732: 1000V	73a		1N3742..44
1S741	Si-Di	=1S732: 100V	73a		1N3735..44
1S742	Si-Di	=1S732: 1200V	73a		1N3743..44
1S743	Si-Di	=1S732: 1500V	73a		—
1S744	Ge-Di	Dem, 40V, 40mA	31a	Oki	AA113, AA119, 1N34, 1N54, 1N60
1S745	Ge-Di	Dem, 50V, 65mA	31a	Oki	AA113, 1N34, 1N54, 1N60
1S746	Ge-Di	Dem, 75V, 45mA	31a	Oki	AA113, 1N34, 1N54, 1N60
1S747	Ge-Di	Dem, 75V, 45mA	31a	Oki	AA113, 1N34, 1N54, 1N60
1S746	Ge-Di	Dem, 20V, 40mA	31a	Oki	AA112..114, 1N34, 1N54, 1N60,++
1S75	Ge-Di	Uni, 30V, 25mA	31a	Njr,Son	AA117..118, AA132..134, 1N34, 1N54,++
1S750(S)	Si-Di	UHF-M, 887MHz	31a	Hit	—

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1S751	Ge-Di	TV-Damper-Di, 200V, 5A	22	Fui	—
1S752(S)	Z-Di	2..3,2V, 0,25W	31	Hit	BZX55/.., BZX79/.., ZPD.., 1N5221..59,++
1S753(S)	Z-Di	=1S752: 3..3,9V	31		—
1S754(S)	Z-Di	=1S752: 3,7..4,5V	31		—
1S755(S)	Z-Di	=1S752: 4,3..5,4V	31		—
1S756(S)	Z-Di	=1S752: 5,2..6,4V	31		—
1S757(S)	Z-Di	=1S752: 6,2..8V	31		—
1S758(S)	Z-Di	=1S752: 7,5..10V	31		—
1S759(S)	Z-Di	=1S752: 9..12V	31		—
1S76	Ge-Di	Dem, 45V, 50mA	31a	Njr, Son	AA113, AA119, 1N34, 1N54, 1N60
1S760(S)	Z-Di	=1S752: 11..14,5V	31		—
1S761(S)	Z-Di	=1S752: 13,5..18V	31		—
1S762(S)	Z-Di	=1S752: 17..21V	31		—
1S763(S)	Z-Di	=1S752: 20..27V	31		—
1S764(S)	Z-Di	=1S752: 25..32V	31		—
1S765(S)	Z-Di	=1S752: 30..39V	31		—
1S766..769	Si-Di	HF-Multipl		Oki	—
1S77(H)	Ge-Di	S, 60V, 60mA	31a	Hit	AA117..118, AA132..133, AAY28
1S770	Si-Di	Gl-L, 100V, 15A(Tc=50°)	75a	Tos	1N3492..95
1S770R	Si-Di	=1S770	75b		1N3492R..95R
1S773(A)	Si-Di	SS, 35V, 0,1A, <4ns	2a	Oki	BA318, BAY38, 1N4148..49, 1N4151,++
1S774(A)	Si-Di	SS, 35V, 0,12A, <4ns	2a	Oki	BA318, BAY38, 1N4148..49, 1N4151,++
1S775(A)	Si-Di	SS, 80V, 0,08A, <3ns	2a	Oki	BAW62, BAX95, 1N4148..49, 1N4151,++
1S776(A)	Si-Di	SS, 130V, 0,1A, <3ns	2a	Oki	—
1S777	Ge-Di	TV-Damper-Di, 200V, 3A	22	Tos	—
1S778	Si-Di	Gl-L, 100V, 12A(Tc=40°)	32a	Inr	BYW88/100, BYX76..81
1S779	Si-Di	Gl-L, 150V, 40A(Tc=104°)	32b	Inr	BYX56/600R, BYX97/300R
1S78(H)	Ge-Di	S, 40V, 80mA	31a	Hit	AA117..118, AA132..133, AAY49
1S780	Si-Di	=1S779: 200V	32b		BYX56/600R, BYX97/300R
1S781	Si-Di	=1S778: 250V	32a		BYW88/300, BYX78..81
1S782	Si-Di	=1S779: 300V	32b		BYX56/600R, BYX97/300R
1S783	Si-Di	=1S779: 400V	32b		BYX56/600R, BYX97/600R
1S784	Si-Di	=1S779: 500V	32b		BYX56/600R, BYX97/600R
1S785	Si-Di	=1S779: 600V	32b		BYX56/600R, BYX97/600R
1S786	Si-Di	=1S779: 600V	32b		BYX56/600R, BYX97/900R
1S787	Si-Di	Gl-L, 100V, 60A(Tc=128°)	32b	Inr	—
1S788	Si-Di	=1S787: 150V	32b		—
1S789	Si-Di	=1S787: 200V	32b		—
1S79(H)	Ge-Di	S, 20V, 0,1A	31a	Hit	AA117..118, AA132..133, AAY49
1S790	Si-Di	Gl-L, 250V, 18A(Tc=40°)	32a	Inr	—
1S791	Si-Di	=1S787: 300V	32b		—
1S792	Si-Di	=1S787: 400V	32b		—
1S793	Si-Di	=1S787: 500V	32b		—
1S794	Si-Di	=1S787: 600V	32b		—
1S795	Si-Di	=1S787: 600V	32b		—
1S796(N)	Z-Di	75V, 5%, 50W(Tc=55°)	23	Tos	—
1S797(N)	Z-Di	=1S796: 95V	23		—
1S798(N)	Z-Di	=1S796: 105V	23		—
1S799(N)	Z-Di	=1S796: 150V	23		—
1S80	Ge-Di	Dem, 30V, 40mA	31a	Hit	AA113, AA119, 1N34, 1N54, 1N60,++
1S800(N)	Z-Di	=1S796: 180V	23		—
1S801	Si-Di	Min, SS, 22V, 0,055A, <4ns	31a	Oki	(BA217, BA317, BAY71, 1N4148..49,++)
1S802	Si-Di	Min, SS, 30V, 0,08A, <4ns	31a	Oki	(BA217, BA317, BAY71, 1N4148..49,++)
1S803	Si-Di	Min, SS, 30V, 0,065A, <4ns	31a	Oki	(BA217, BA317, BAY71, 1N4148..49,++)
1S804	Si-Di	Min, SS, 50V, 0,06A, <4ns	31a	Oki	(BA218, BA318, BAY38, 1N4148..49,++)
1S805	Si-Di	Min, SS, 50V, 0,065A, <2ns	31a	Oki	(BA218, BA318, BAY38, 1N4148..49,++)
1S806	Si-Di	Min, SS, 50V, 0,065A, <2ns	31a	Oki	(BA218, BA318, BAY38, 1N4148..49,++)
1S807	Si-Di	Min, SS, 75V, 0,085A, <2ns	31a	Oki	(BAW62, BAX95, BAW76, 1N4148..49,++)
1S808	Si-Di	Min, SS, 100V, 0,085A, <2ns	31a	Oki	(BA219, BAX96, 1N4148..49, 1N4151,++)
1S81	Si-Di	Uni, 230V, 0,06A	31a	Tos	BA147/230, BA157..159, BAY21,++
1S810	Ge-Di	Uni, 100V, 0,1A	31a	Tos	AA117..118, AA132..133, 1N634..35
1S811	Si-Di	Gl, Uni, 250V, 0,5A(Tc=100°)	31a	Fjd	BY126..127, BY133..134, 1N4004..07,++
1S812	Si-Di	=1S811: 400V	31a		BY126..127, BY133..134, 1N4004..07,++
1S813	Si-Di	=1S811: 600V	31a		BY127, BY133, BY227, 1N4006..07,++
1S814	Si-Di	=1S811: 1000V	31a		BY127, BY133, BY227, 1N4007,++
1S815	Si-Di	=1S811: 1200V	31a		BY127, BY133, BY227, GP100,++

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1S818	Si-Di	Gl, Uni, 250V, 1A(Tc=120°)	34	Fjd	BY252..255, BYW17/400, 1N5404..08, ++
1S817	Si-Di	=1S818: 400V	34		BY252..255, BYW17/400, 1N5404..08, ++
1S818	Si-Di	=1S816: 800V	34		BY254..255, BYW17/800, 1N5407..08, ++
1S819	Si-Di	=1S818: 1000V	34		BY228, BY255, BYW17/1000, 1N5408, ++
1S82	Ge-Di	Uni, 50V, 50mA	31a	Tos	AA117..118, AA132..134, 1N34, 1N54, ++
1S820	Si-Di	=1S816: 1200V	34		BY228, BY255, BYW17/1200, ++
1S821	Si-Di	Gl-L, 250V, 2,5A(Tc=120°)	≈32b	Fjd	BYX38/300R, BYX39/600R
1S822	Si-Di	=1S821: 400V	≈32b		BYX38/600R, BYX39/600R
1S823	Si-Di	=1S821: 600V	≈32b		BYX38/900R, BYX39/600R
1S824	Si-Di	=1S821: 1000V	≈32b		BYX38/1200R, BYX39/1000R
1S825	Si-Di	=1S821: 1200V	≈32b		BYX38/1200R, BYX39/1200R
1S826	Si-Di	Gl-L, 250V, 6A(Tc=120°)	73b	Fjd	BYX38/300R, BYX39/600R
1S827	Si-Di	=1S826: 400V	73b		BYX38/600R, BYX39/600R
1S826	Si-Di	=1S826: 800V	73b		BYX38/900R, BYX39/600R
1S829	Si-Di	=1S826: 1000V	73b		BYX38/1200R, BYX39/1000R
1S83(H)	Ge-Di	Gl, Uni, 80V, 0,2A	2	Hit	1N270
1S830	Si-Di	=1S826: 1200V	73b		BYX38/1200R, BYX39/1200R
1S831	Si-Di	Gl-L, 250V, 10A(120°)	73b	Fjd	BYX42/300R, BYX98/300R
1S832	Si-Di	=1S831: 400V	73b		BYX42/600R, BYX98/600R
1S833	Si-Di	=1S831: 600V	73b		BYX42/900R, BYX98/900R
1S834	Si-Di	=1S831: 1000V	73b		BYX42/1200R, BYX98/1200R
1S835	Si-Di	=1S831: 1200V	73b		BYX42/1200R, BYX98/1200R
1S836	Si-Di	Gl-L, 250V, 20A(Tc=120°)	73b	Fjd	D24/400B
1S837	Si-Di	=1S836: 400V	73b		D24/400B
1S836	Si-Di	=1S836: 600V	73b		D24/800B
1S839	Si-Di	=1S836: 1000V	73b		D24/1000B
1S84(H)	Ge-Di	Gl, S, 200V, 0,1A	2	Hit	1N39
1S840	Si-Di	=1S836: 1200V	73b		D24/1200B
1S841	Si-Di	Gl, Uni, 100V, 1A	34a	Nec	BY126..127, BY133..134, 1N4002..07, ++
1S842	Si-Di	=1S841: 200V	34a		BY126..127, BY133..134, 1N4003..07, ++
1S843	Si-Di	=1S841: 300V	34a		BY126..127, BY133..134, 1N4004..07, ++
1S844(N)	Si-Di	=1S841: 400V	34a	Nec,Fjd,Shi	BY126..127, BY133..134, 1N4004..07, ++
1S845	Si-Di	=1S841: 500V	34a		BY126..127, BY133..134, 1N4005..07, ++
1S846(N)	Si-Di	=1S841: 600V	34a	Nec,Fjd,Shi	BY126..127, BY133..134, 1N4005..07, ++
1S847	Si-Di	=1S841: 700V	34a		BY127, BY133, BY227, 1N4006..07, ++
1S848(N)	Si-Di	=1S841: 600V	34a	Nec,FjdShi	BY127, BY133, BY227, 1N4006..07, ++
1S849	Si-Di	=1S841+C9406: 900V	34a		BY127, BY133, BY227, 1N4007, ++
1S85(H)	C-Di	AFC	31a	Hit	BA124..125, BB119, 1S2790, 1SV50, ++
1S850(N)	Si-Di	=1S841: 1000V	34a	Nec,Fjd,Shi	BY127, BY133, BY227, 1N4007, ++
1S851	Si-Di	=1S841: 1200V	34a		BY127, BY133, BY227, GP10Q, ++
1S852	Si-Di	=1S841: 1500V	34a		BY350/1500, BY400, BY448, GP10W
1S853	Si-Di	Gl, 300V, 2,5A		Sak	(BY205/400, BY229/400, BYX49/300, ++)
1S854	Si-Di	=1S853: 400V			(BY205/400, BY229/400, BYX49/600, ++)
1S855	Si-Di	=1S853: 500V			(BY205/600, BY229/600, BYX49/600, ++)
1S856	Si-Di	=1S853: 600V			(BY205/600, BY229/600, BYX49/600, ++)
1S857	Si-Di	=1S853: 700V			(BY205/600, BY229/800, BYX49/900, ++)
1S856	Si-Di	=1S853: 600V			(BY205/600, BY229/600, BYX49/900, ++)
1S859	Si-Di	=1S853: 900V			(BY205/1000, BY229/1000, BYX49/1200, ++)
1S86	C-Di	FM/VHF-AFC	31a	Tos	BA124..125, BB119, 1S2790, 1SV50, ++
1S880	Si-Di	=1S853: 1000V			(BY205/1000, BY229/1000, BYX49/1200, ++)
1S881	Si-Di	Gl-L, 100V, 10A(Tc=40°)	75a	Sak	1N3492..95
1S861R	Si-Di	=1S861:	75b		1N3492R..95R
1S863	Si-Di	Gl-L, 300V, 6A	73a	Sak	BYX42/300, BYX98/300
1S864	Si-Di	=1S883: 400V	73a		BYX42/600, BYX98/600
1S865	Si-Di	=1S883: 500V	73a		BYX42/600, BYX98/600
1S866	Si-Di	=1S883: 600V	73a		BYX42/600, BYX98/600
1S867	Si-Di	=1S883: 700V	73a		BYX42/900, BYX98/900
1S888	Si-Di	=1S883: 600V	73a		BYX42/900, BYX98/900
1S869	Si-Di	=1S883: 900V	73a		BYX42/900, BYX98/900
1S87	Ge-Di	S, 20V, 0,1A, <120ns	31a	Tos	AAY49, AAZ15, AAZ17
1S870	Si-Di	=1S863: 1000V	73a		BYX42/1200, BYX98/1200
1S871	Si-Di	Gl, Uni, 400V, 0,15A	31a	Sak	BA157..159, BY203/12, BY204/4, ++
1S871A	Si-Di	=1S871: 600V	31a		BA158..159, BY203/12, BY204/8, ++
1S871B	Si-Di	=1S871: 600V	31a		BA158..159, BY203/12, BY204/8, ++
1S871C	Si-Di	=1S871: 1000V	31a		BA159, BAY90, BY203/12, BY204/10, ++
1S871D	Si-Di	=1S871: 1200V	31a		BAY91, BY203/12, SHG1,5

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1S871E	Si-Di	=1S871: 1400V	31a		BAY91, BY203/16, SHG1,5
1S871F	Si-Di	=1S871: 1600V	31a		BAY91, BY203/18, SHG2
1S871G	Si-Di	=1S871: 1800V	31a		BAY91, BY203/20, SHG2
1S871H	Si-Di	=1S871: 2000V	31a		BAY91, BY203/20, SHG2
1S872	Si-Di	GI, Uni, 400V, 0,25A	31a	Sak	BA157..159, BY204/4, BY203/12, ++
1S872A	Si-Di	=1S872: 600V	31a		BA158..159, BY204/6, BY203/12, ++
1S872B	Si-Di	=1S872: 800V	31a		BA158..159, BY204/8, BY203/12, ++
1S872C	Si-Di	=1S872: 1000V	31a		BA158, BAY90, BY204/10, BY203/12, ++
1S872D	Si-Di	=1S872: 1200V	31a		BAY91, BY203/12, BY268..269, ++
1S873	Si-Di	GI-L, 300V, 17A	73a	Sak	BYX96/300
1S874	Si-Di	=1S873: 400V	73a		BYX96/600
1S875	Si-Di	=1S873: 500V	73a		BYX96/600
1S875	Si-Di	=1S873: 600V	73a		BYX96/600
1S877	Si-Di	=1S873: 700V	73a		BYX96/900
1S878	Si-Di	=1S873: 800V	73a		BYX96/900
1S879	Si-Di	=1S873: 900V	73a		BYX96/900
1S88	Ge-Di	=1S87: <240ns	31a		AAY49, AAZ15, AAZ17
1S880	Si-Di	=1S873: 1000V	73a		BYX96/1200
1S881	Si-Di	GI, Uni, 400V, 0,5A	31a	Sak	BY126..127, BY133..134, 1N4004..07, ++
1SS81A	Si-Di	=1S881: 600V	31a		BY126..127, BY133..134, 1N4005..07, ++
1S881B	Si-Di	=1S881: 800V	31a		BY127, BY133, BY227, 1N4006..07, ++
1S881C	Si-Di	=1S881: 1000V	31a		BY127, BY133, BY227, 1N4007, ++
1S881D	Si-Di	=1S881: 1200V	31a		BY127, BY133, BY227, BY268..269, ++
1S881E	Si-Di	=1S881: 1400V	31a		BY268..269, GP10V, DM513, EM518, ++
1S882	Si-Di	GI, Uni, 400V 0,75A	31a	Sak	BY126..127, BY133..134, 1N4004..07, ++
1S882A	Si-Di	=1S882: 600V	31a		BY126..127, BY133..134, 1N4005..07, ++
1S882B	Si-Di	=1S882: 800V	31a		BY127, BY133, BY227, 1N4006..07, ++
1S882C	Si-Di	=1S882: 1000V	31a		BY127, BY133, BY227, 1N4007, ++
1S882D	Si-Di	=1S882: 1200V	31a		BY127, BY133, BY227, BY268..269, ++
1S882E	Si-Di	=1S882: 1400V	31a		BY268..269, GP10V, DM513, EM518, ++
1S883	Si-Di	GI-L, 300V, 100A	73a	Sak	1N3290..97
1S884	Si-Di	=1S883: 400V	73a		1N3291..97
1S885	Si-Di	=1S883: 500V	73a		1N3292..97
1S886	Si-Di	=1S883: 600V	73a		1N3293..97
1S887	Si-Di	=1S883: 700V	73a		1N3294..97
1S888	Si-Di	=1S883: 800V	73a		1N3294..97
1S889	Si-Di	=1S883: 900V	73a		1N3295..97
1S89	Ge-Di	=1S87: <340ns	31a		AAY49, AAZ15, AAZ17
1S890	Si-Di	=1S883: 1000V	73a		1N3295..97
1S891	C-Di	AFC	31a	Sak	BA124..125, BB119, 1S2790, 1SV50, ++
1S892	C-Di	AFC	31a	Sak	BA124..125, BB119, 1S2790, 1SV50, ++
1S893	C-Di	AFC	31a	Sak	BA124..125, BB119, 1S2790, 1SV50, ++
1S894	Si-Di	kV-GI, 6kV, 0,03A	31a	Sak	CY7, HS6
1S895	Si-Di	=1S894: 6kV	31a		CY10, HS8
1S896	Si-Di	=1S894: 10kV	31a		CY10, HS8
1S897	Si-Di	=1S894: 12kV	31a		HS10
1S90	Si-Di	GI, 150V, 0,3A	34a	Tos	BY126..127, BY133..135, 1N4003..07, ++
1S90R..99R	Si-Di	=1S90..99:	34b		→1S90..99
1S91	Si-Di	=1S90: 200V	34a		BY126..127, BY133..134, 1N4003..07, ++
1S92	Si-Di	=1S90: 300V	34a		BY126..127, BY133..134, 1N4004..07, ++
1S920[Fch, Tix]	Si-Di	=BA187	31a	Fch, Tix	→BA187
1S921[Fch, Tix]	Si-Di	=BA188	31a	Fch, Tix	→BA188
1S921[Japan]	Si-Di	GI, Uni, 200V, 1,5A	34	Shi	BY226..227, BY251..255, 1N5393..99, ++
1S922[Fch, Tix]	Si-Di	=BA189	31a	Fch, Tix	→BA189
1S922[Japan]	Si-Di	=1S921[Japan]: 400V	34	Shi	BY226..227, BY252..255, 1N5395..99, ++
1S923[Fch, Tix]	Si-Di	=BA190+C9453	31a	Fch, Tix	→BA190
1S923[Japan]	Si-Di	=1S921[Japan]: 800V	34	Shi	BY226..227, BY253..255, 1N5397..99, ++
1S924[Japan]	Si-Di	=1S921[Japan]: 800V	34	Shi	BY227, BY254..255, 1N5398..99, ++
1S925[Japan]	Si-Di	=1S921[Japan]: 1000V	34		BY227, BY255, BYX86..87, 1N5399, ++
1S928	Si-Di	GI-L, 200V, 20A(Tc=90°)	73a	Shi	1N4525..30
1S927	Si-Di	=1S926: 400V	73a		1N4526..30
1S928	Si-Di	=1S926: 800V	73a		1N4527..30
1S929	Si-Di	=1S926: 800V	73a		1N4528..30
1S93	Si-Di	=1S90: 400V	34a		BY126..127, BY133..134, 1N4004..07, ++
1S930	Si-Di	=1S926: 1000V	73a		1N4529..30
1S931	Si-Di	GI-L, 200V, 50A(Tc=79°)	73a	Shi	1N3289..97

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1S932	Si-Di	=1S931: 400V	73a		1N3291..97
1S933	Si-Di	=1S931: 600V	73a		1N3293..97
1S934	Si-Di	=1S931: 300V	73a		1N3294..97
1S935	Si-Di	=1S931: 1000V	73a		1N3295..97
1S936[Japan]	Si-Di	GI-L, 200V, 100A(Tc=91°)	73a	Shi	1N3289..97
1S937[Japan]	Si-Di	=1S936[Japan]: 400V	73a		1N3291..97
1S936[Japan]	Si-Di	=1S936[Japan]: 600V	73a		1N3293.97
1S939[Japan]	Si-Di	=1S936[Japan]: 600V	73a		1N3294..97
1S94	Si-Di	=1S90: 500V	34a		BY 126..127, BY 133.134, 1N4005..07,++
1S940[Japan]	Si-Di	=1S936[Japan]: 1000V	73a		1N3295..97
1S940[Texas[	Si-Di	Uni, 30V, 0,05A	31a	Tix	BA 147/50, BA 187 190, 1N5606 09,++
1S941[Japan]	Si-Di	GI-L, 200V, 200A(Tc=83°)		Shi	—
1S941[Texas]	Si-Di	=1S940[Texas]: 50V	31a	Tix	BA 147/50, BA 187. 190, 1N5606..09,++
1S942[Japan]	Si-Di	=1S941[Japan]: 400V		Shi	—
13942[Texas]	Si-Di	=1S940[Texas]: 75V	31a	Tix	BA 147/100, BA 188..180, 1N5606..09,++
1S943[Japan]	Si-Di	=1S941[Japan]: 600V		Shi	—
1S944[Japan]	Si-Di	=1S941[Japan]: 600V			—
1S945[Japan]	Si-Di	=1S941[Japan]: 1000V			—
1S946	Si-Di	GI, Uni, 200V, 0,6A	31a	Shi	BY 126..127, BY 133..134, 1N4003..07,++
1S947	Si-Di	=1S947: 400V	31a		BY 126 127, BY 133..134, 1N4004..07,++
1S948	Si-Di	=1S947: 600V	31a		BY 126..127, BY 133..134, 1N4005..07,++
1S949	Si-Di	=1S947: 600V	31a		BY 127, BY 133, BY 227, 1N4006. 07,++
1S95	Si-Di	=1S90: 600V	34a		BY 126..127, BY 133..134, 1N4005..07,++
1S950	Si-Di	=1S947: 1000V	31a		BY 127, BY 133, BY 227, 1N4007,++
1S951	Si-Di	SS, 35V, 0,1A, <3ns	31a	Nec	BA318, BAY38, 1N4148..49, 1N4151,++
1S952	Si-Di	SS, 35V, 0,15A, <3ns	31a	Nec	BA318, BAY36, 1N4148..49, 1N4151,++
1S953	Si-Di	SS, 35V, 0,1A, <3ns	31a	Nec	BA318, BAY36, 1N4148..49, 1N4151,++
1S954	Si-Di	SS, 75V, 0,2A, <3ns	31a	Nec	BAW62, BAX95, 1N4148..49, 1N4151,++
1S955	Si-Di	SS, 100V, 0,2A, <3ns	31a	Nec	BAW62, BAX95, 1N4148..49, 1N4151,++
1S956	Si-Di	GI, 200V, 1,5A	34b	Hit	BY 226..227, BY 251 .255, 1N5393..99,++
1S957	Si-Di	=1S956: 400V	34b		BY 226 .227, BY 252..255, 1N5395..99,++
1S956	Si-Di	=1S956: 600V	34b		BY 226..227, BY 253 .255, 1N5397..99,++
1S959	Si-Di	=1S956: 600V	34b		BY 227, BY 254..255, 1N5398 99,++
1S96	Si-Di	=1S90: 700V	34a		BY 127, BY 133, BY 227, 1N4006..07,++
1S960	Si-Di	=1S956: 1000V	34b		BY 227, BY 255, BYX86. 8+F94997, 1N5399,++
1S961	Si-Di	GI, 200V, 3A	≈34	Hit	(BY 205/200, BY 229/200, BYX 49/300,++)
1S962	Si-Di	=1S961: 400V	≈34		[BY 205/400, BY 229/400, BYX 49/600,++)
1S963	Si-Di	=1S961: 600V	≈34		[BY 205/800, BY 229/600, BYX 49/600,++)
1S964	Si-Di	=1S961: 800V	≈34		(BY 205/800, BY 229/600, BYX 49/900,++)
1S965	Si-Di	=1S961: 1000V	≈34		[BY 205/1000, BY 229/1000, BYX 49/1200,++
1S966	Si-Di	GI-L, 200V, 20A	32		1N4525..30
1S967	Si-Di	=1S966: 400V	32		1N4526..30
1S968	Si-Di	=1S966: 600V	32		1N4527. 30
1S969	Si-Di	=1S966: 600V	32		1N4528 30
1S97	Si-Di	=1S90: 600V	34a		BY 127, BY 133, BY 227, 1N4006..07,++
1S970	Si-Di	=1S968: 1000V	32		1N4529..30
1S971	Si-Di	GI-L, 500V, 280A	73b	Hit	—
1S972	Si-Di	=1S971: 600V	73b		—
1S973	Si-Di	=1S971: 600V	73b		—
1S974	Si-Di	=1S971: 1000V	73b		—
1S975	Si-Di	=1S971: 1300V	73b		—
1S976	Si-Di	=1S971: 1500V	73b		—
1S977	Si-Di	SS, 35V, 0,06A, <2,5ns	34	Oki	BA318, BAY36, 1N4148 .49, 1N4151,++
1S978	Si-Di	=1S977: 50V	34	Oki	BA318, BAY36, 1N4148..49, 1N4151,++
1S96	Si-Di	=1S90: 900V	34a		BY 127, BY 133, BY 227, 1N4007,++
1S961	Si-Di	SS, 30V, 0,045A, <2,5ns	31a	Oki	BA318, BAY38, 1N4148..49, 1N4151,++
1S962	Si-Di	SS, 30V, 0,05A, <2,5ns	31a	Oki	BA318, BAY38, 1N4148..49, 1N4151,++
1S963	Si-Di	SS, 30V, 0,06A, <2,5ns	31a	Oki	BA318, BAY36, 1N4148..49, 1N4151,++
1S964	Si-Di	SS, 50V, 0,05A, <2ns	31a	Oki	BA318, BAY36, 1N4148 .49, 1N4151,++
1S985	Si-Di	SS, 50V, 0,06A, <2ns	31a	Oki	BA318, BAY36, 1N4148..49, 1N4151,++
1S986	Si-Di	SS, 50V, 0,06A, <2ns	31a	Oki	BA318, BAY36, 1N4148..49, 1N4151,++
1S967	Si-Di	SS, 100V, 0,06A, <2ns	31a	Oki	BAW62, BAX95, 1N4148..49, 1N4151,++
1S988	Si-Di	SS, 100V, 0,06A, <2ns	31a	Oki	BAW62, BAX95, 1N4148..49, 1N4151,++
1S989	Z-Di	17. 21V, 3W	32a	Tos	BZX98/C18, BZY93/C18, ZL18, 1N2982
1S99	Si-Di	=1S90: 1000V	34a		BY 127, BY 133, BY 227, 1N4007,++
1S990(A)	Si-St	0,6..0,8V, 0,25W	31a	Njr	BA220, BZ102/0V7, BZX55/C0V8, ZPD1

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1S991(A)	Si-St	=1S990: 1,3..1,5V	31a		BZ102/1V4, BZX75/C1V4, ZTE1,5
1S992	Si-St	=1S990: 1,4..2,6V	31a		BZ102/2V1, BZX75/C2V1, ZTE2
1S993	Si-St	=1S990: 2,4..3,6V	31a		—
1S994	Si-St	=1S990: 3,4..4,6V	31a		—
1S995	Si-Di	35V	31a	Njr	—
1S996(A, B)	Si-Di	5..10V, 0,1..0,15A	31a	Njr	—
1S997	Si-Di	10V, 0,1A	31a	Njr	—
1S998(A, B)	Si-Di	5..10V, 0,1..0,15A	31a	Njr	—
1S999	Si-St	0,55..0,75V, 0,05W	31a	Njr	BA220, BZ102/0V7, BZX55/C0V8, ZPD1,++
1SP..1SS		**1SP..1SS**			
1SP	Si-N	=2SC3130-P (Typ-Code/Stempel/marking)	35		→2SC3130
1SP	Si-N	=2SC3935-P(Typ-Code/Stempel/marking)	35(2mm)		→2SC3935
1SQ	Si-N	=2SC3130-Q (Typ-Code/Stempel/marking)	35		→2SC3130
1SQ	Si-N	=2SC3935-Q (Typ-Code/Stempel/marking)	35(2mm)		→2SC3935
1SR	Si-N	=2SC3130-R (Typ-Code/Stempel/marking)	35		→2SC3130
1SR	Si-N	=2SC3935-R (Typ-Code/Stempel/marking)	35(2mm)		→2SC3935
1SR1	Si-Br				B30C1500, etc.
1SR124-..A	Si-Di	Gl/S, 100..400V, 1A, <400ns	31a	Rhm	BYV12..18, RGP10B..M, RGP15B..M,++
1SR124-100A	Si-Di	Gl/S, 100V, 1A, <400ns	31a	Rhm	BYT52B..M, BYV12..16, RGP10B..M,++
1SR139-..	Si-Di	Gl, 100..600V, 1A	31a	Rhm	BY126..127, BY133..135, 1N4002..07,++
1SR153-..	Si-Di	Gl/S, 100..400V, 0,8A, <400ns	31a	Rhm	BYT52B..M, BYV12..16, RGP10B..M,++
1SR154-..	Si-Di	=1S35-..: SMD	71a(5mm)	Rhm	—
1SR156-..	Si-Di	=1S153-..: SMD	71a(5mm)	Rhm	—
1SR159-200	Si-Di	S, 200V, 1A, <50ns	71a(5mm)	Rhm	—
1SR35-..(A)	Si-Di	Gl, 100..400V, 1A	31a	Rhm	BY126..127, BY133..135, 1N4002..07,++
1SS100	Si-Di	UHF/SHF-Mixer		Tos	—
1SS101	Si-Di	Schottky-Di, 70V, 15mA	31a	Nec	BAR28, HSS102, 1N5711
1SS102	Si-Di	SS, 125V, 0,15A, <3ns	31a	Nec	(BA203)
1SS103	C-Di	VHF-Band-S	71a(4mm)	Nec	BA182, BA243, BA283, BA483..484, ++
1SS104	Si-Di	Uni, 35V, 0,1A	31a	Tos	BA127, BA147/50, BA187..190, BA215++
1SS106	Si-Di	Schottky-Di, Dem, SS, 11V, 0,03A	31a	Hit	BAR10, BAT19
1SS107	Si-Di	Schottky-Di, 22V, 15mA	31a	Hit	BAR10, 1N5712
1SS108	Si-Di	Schottky-Di, 35V, 15mA	31a	Hit	HSS100..102, 1S1992
1SS109	Si-Di	Uni, 90V, 0,15A	31a	Hit	BA147/100, BA189..190, BAY19..21, ++
1SS11	GaAs-Di	UHF-M, 9375MHz		Nec	—
1SS110	C-Di	VHF-Band-S	31a	Hit	BA182, BA243, BA283, BA483..484, ++
1SS111	Si-Di	SS, 20V, 0,15A, <2ns	31a	Hit	BAX80, BAY95, 1N4148..49, 1N4446..48++
1SS112	Si-Di	=1SS111: 40V	31a		BAX80, BAY95, 1N4148..49, 1N4446..48++
1SS113	Si-Di	=1SS111: 60V	31a		BAW62, BAX95, 1N4148..49, 1N4446..48++
1SS114	Si-Di	=1SS111: 80V	31a		BAW62, BAX95, 1N4148..49, 1N4448..48++
1SS115	Si-Di	=1SS111: 100V	31a		BAW62, BAX95, 1N4148..49, 1N4446..48++
1SS116	Si-Di	=1SS111: 120V	31a		—
1SS117	Si-Di	SS, 35V, 0,1A, <3ns	31a	Hit	BA318, BAY38, 1N4148..49, 1N4448..49++
1SS118	Si-Di	SS, 75V, 0,2A, <3ns	31a	Hit	BAW62, BAX95, 1N4148..49, 1N4448..49++
1SS119	Si-Di	SS, 35V, 0,15A, <3,5ns	31a	Hit	BA318, BAY38, 1N4148..49, 1N4448..49++
1SS12	GaAs-Di	UHF-M, 3060MHz		Nec	—
1SS120	Si-Di	=1SS119: 70V	31a	Hit	BAW62, BAX95, 1N4148..49, 1N4446..49++
1SS121	Si-Di	S, 75V, 0,2A, <50ns	31a	Hit	BAV19..21, BAW+F957849, BAY43, BAY72, ++
1SS122(H)	Si-Di	Uni, S, 400V, 0,15A, <10µs	31a	Hit	BA157..159, BA199/450, BAY89..91, ++
1SS123	Si-Di	SMD, Dual, SS, 70V, 0,1A, <9ns	35t	Nec	—
1SS124	Si-Di	Schottky-Di, UHF-Dem, 3V, 30mA, 24GHz	Koax	Nec	—
1SS125	Si-Di	Schottky-Di, UHF-Dem, 22V, 50mA, 10GHz	Koax	Nec	—
1SS13	GaAs-Di	UHF-M, 9375MHz		Nec	—
1SS130	Si-Di	SS, 100V, 0,13A, <4ns	31a	Rhm	1N4148..49, 1N4448..49, 1SS115..116
1SS131	Si-Di	SS, 90V, 0,13A, <4ns	31a	Rhm	1N4148..49, 1N4448..49, 1SS115..116
1SS132	Si-Di	SS, 55V, 0,12A, <4ns	31a	Rhm	BAW62, BAX95, 1N4148..49, 1N4446..49++
1SS133	Si-Di	SS, 40V, 0,11A, <4ns	31a	Rhm	BA318, BAY38, 1N4148..49, 1N4448..49++
1SS134	Si-Di	SS, 40V, 0,05A, <3ns	31a	Rhm	BA318, BAY38, 1N4148..49, 1N4446..49++
1SS135	C-Di	VHF-Band-S	31a	Rhm	BA182, BA243, BA283, BA483..484, ++
1SS136	Si-Di	SS, 75V, 0,2A, <2ns	31a	Rhm	BAW62, BAX95, 1N4148..49, 1N4448..49++
1SS137	Si-Di	=1SS136: 55V	31a	Rhm	BAW62, BAX95, 1N4148..49, 1N4446..49++
1SS138	Si-Di	=1SS136: 40V	31a	Rhm	BA318, BAY38, 1N4148..49, 1N4448..49++
1SS139	Si-Di	S, 90V, 0,13A, <50ns	31a	Rhm	BAV19..21, BAW49, BAY43, BAY72, ++
1SS14	GaAs-Di	UHF-M, 10GHz		Nec	—
1SS140	Si-Di	S, 55V, 0,12A, <50ns	31a	Rhm	BAV18..21, BAW49, BAY42, BAY72, ++

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1SS141	Si-Di	S, 40V, 0,11A, <50ns	31a	Rhm	BAV16..21, BAW49, BAY41, BAY72, ++
1SS142	Si-Di	S, Uni, 300V, 0,2A, <400ns	31a	Rhm	BA157..159, BY204/4, BY206. 207, ++
1SS143	Si-Di	=1SS142: 250V	31a	Rhm	BA157..159, BY204/4, BY206..207, ++
1SS144	Si-Di	=1SS142: 200V	31a	Rhm	BA157..159, BY204/4, BY206. 207, ++
1SS145	Si-Di	=1SS142	31a	Rhm	BA157..159, BY204/4, BY206. 207, ++
1SS146	Si-Di	=1SS143	31a	Rhm	BA157..159, BY204/4, BY206..207, ++
1SS147	Si-Di	=1SS144	31a	Rhm	BA157..159, BY204/4, BY206..207, ++
1SS146	Si-Di	SS, 35V, 0,1A, <4ns	31a	Tos	BA316, BAY38, 1N4148..49, 1N4446..49++
1SS149	Si-Di	Uni, 250V, 0,15A, <5µs	31a	Hit	BA157..159, BY204/4, BY206..207, ++
1SS15	GaAs-Di	UHF-M, 21GHz		Nec	—
1SS150	C-Di	VHF-Band-S	31a	Hit	BA182, BA243, BS283, BA483..484, ++
1SS151	Si-Di	Schottky-Di, Dem, S, 4V, 30mA	31a	Hit	BA480..481, BAR19, BAT29
1SS152	C-Di	VHF-Band-S	31a	Hit	BA182, BA243, BS283, BA483..484, ++
1SS153	C-Di	SMD, VHF-Band-S	35p	Nec	—
1SS154	Si-Di	SMD, UHF, S, 6V, 0,03A, 0,8pF	35c	Tos	—
1SS155	C-Di	(Band-S)	31a	Tos	—
1SS157	Ge-Di	Dem, 40V, 50mA	31a	Say	AA113, AA119, 1N34, 1N54, 1N60
1SS158	Ge-Di	Dem, 50V, 50mA	31a	Say	AA113, 1N34, 1N54, 1N60
1SS16	Si-Di	UHF-M, 855MHz	31a	Nec	—
1SS161	C-Di	VHF-Band-S	31a	Njr	BA182, BA243, BA283, BA483..484, ++
1SS162	C-Di	UHF-Band-S	31a	Njr	BA244, BA282, BA482
1SS163	Si-Di	SS, 35V, 0,15A, <4ns	31a	Hit	BA316, BAY38, 1N4148..49, 1N4448..49++
1SS164	Si-Di	=1SS163: 70V	31a	Hit	BAW62, BAX95, 1N4148..49, 1N4448..49++
1SS165	Si-Di	Schottky, CATV-M, 12V, 15mA, <1pF(0V)	31a	Hit	BAR10..11, 1N5712
1SS166	Si-Di	=1SS165: <1,2pF(0V)	31a	Hit	BAR10..11, 1N5712
1SS166A	Si-Di	=1SS165: <0,8pF(0V)	31a		BAR10..11, 1N5712
1SS166	C-Di	VHF-Tuner, Band-S	31a	Hit	BA182, BA243, BA283, BA483..484, ++
1SS172	Si-Di	S, 120V, 0,7A, <20ns	31a	Hit	—
1SS173	Si-Di	S, 35V, 0,1A, <12ns	31a	Hit	BA316, BAY17, 1N4148..49, 1SS113, ++
1SS174	Si-Di	Schottky-Di, TV-UHF-M, 3V, 30mA	31a	Hit	BA480..481, BAR19, BAT29
1SS175	Si-Di	S, 75V, 0,15A, <100ns	31a	Hit	BA201, BAV19..21, 1N4148..4149, ++
1SS175A	Si-Di	=1SS175: 100V	31a		BA202, BAV19..21, 1N4148..4149, ++
1SS176	Si-Di	SS, 35V, 0,1A, <4ns	31a	Tos	BA316, BAY38, BAY71, 1N4148..49, ++
1SS177	Si-Di	=1SS176: 55V	31a		BA316, BAX80, BAY38, 1N4148..49, ++
1SS178	Si-Di	=1SS176: 90V	31a		BA219, 1SS115, 1N4148..49, 1N4446..49++
1SS181	Si-Di	SMD, Dual, SS, 85V, 0,1A, <4ns	35n	Tos	BAV70
1SS184	Si-Di	=1SS181:	35l		BAW56
1SS187	Si-Di	SMD, SS, 85V, 0,1A, <4ns	35g	Tos	—
1SS190	Si-Di	=1SS187:	35d	Tos	—
1SS193	Si-Di	=1SS187:	35p	Tos	—
1SS196	Si-Di	=1SS187:	35c	Tos	—
1SS197	C-Di	VHF-Tuner, Band-S	31a	Hit	BA182, BA243, BA283, BA483..484, ++
1SS198	Si-Di	Schottky-Di, Dem, S, 10V, 30mA	31a	Hit	BAR10..11, 1N5712, 1SS106
1SS199	Si-Di	Schottky-Di, Dem, S, 30V, 15mA	S1a	Hit	BAT81, HSS101, 1S1992, 1SS106
1SS200	Si-Di	Dual, 85V, 0,1A, <4ns	41h	Tos	—
1SS201	Si-Di	=1SS200:	41j	Tos	—
1SS202	Si-Di	SS, 35V, 0,1A, <3ns	31a	Nec	BAW62, BAX95, 1N4148..49, 1N4448..49++
1SS202(1)	Si-Di	=1SS202: 100V	31a		1N4148..49, 1N4448..49, 1SS115..116
1SS205	Si-Di	=1SS53	31a	Nec	→1SS53
1SS206	Si-Di	=1SS54	31a	Nec	→1SS54
1SS207	Si-Di	=1SS55	31a	Nec	→1SS55
1SS220	Si-Di	SMD, SS, 70V, 0,1A, <3ns	35p	Nec	—
1SS221	Si-Di	=1SS220: 100V	35p	Nec	—
1SS222	Si-Di	=1SS220:	35g	Nec	—
1SS223	Si-Di	=1SS220: 100V	35g	Nec	—
1SS226	Si-Di	SMD, Dual, 85V, 0,1A, <4ns	35l	Tos	—
1SS228	Si-Di	Schottky-Di, TV-UHF-M, 3V, 30mA	31a	Hit	BA480..481, BAR19, BAT29
1SS23	Si-Di	Schottky-Di, 12V, 0,1A		Nec	BAT47
1SS233	Si-Di	Dual, 35V, 0,1A, <3ns	40e	Nec	MC921
1SS234	Si-Di	=1SS233: 75V	40e	Nec	MC921
1SS235	Si-Di	=1SS233:	40h	Nec	MC911
1SS236	Si-Di	=1SS233: 75V	40h	Nec	MC911
1SS237(1)	Si-Di	Schottky, UHF-M, 10V, 35mA, <1pF(0V)	31a	Nec	BAT19, BAT45, 1SS66, 1SS106
1SS238	C-Di	VHF-Tuner, Band-S	31a	Tos	BA182, BA243, BA283, BA483..484, ++
1SS239	Si-Di	Schottky-Di, VHF/UHF, 6V, 30mA	71a(2,7mm)	Tos	—
1SS24	Ge-Di	Dem, 40V, 50mA	31a	Unz	AA113, 1N34, 1N54, 1N60

1SS241	C-Di	VHF-Band-S, 30V, 0,1A, <1,2pF, <0,9Ω	71a(2,7mm)	Tos	BA582
1SS242	C-Di	Schottky-Di, VHF-M/Band-S, 5V, 30mA	71a(2,7mm)	Tos	—
1SS244	Si-Di	S, 250V, 0,2A, <75ns	31a	Rhm	BA198, BAV21, 1SS83
1SS245	Si-Di	=1SS244	31a	Rhm	BA198, BAV21, 1SS83
1SS247	Si-Di	S, 250V, 0,2A, <60ns	31a	Tos	BA198, BAV21 (BA157..159, BY206..207)
1SS248	Si-Di	=1SS247: 300V	31a	Tos	1SS83 (BA157..159, BY206..207)
1SS25	Ge-Di	Dem, 40V, 50mA	31a	Unz	AA113, 1N34, 1N54, 1N60
1SS250	Si-Di	SMD, 250V, 0,1A, <60ns	35p	Tos	BAS21
1SS252	Si-Di	=1SS131	31a	Rhm	→1SS131
1SS253	Si-Di	=1SS132	31a	Rhm	→1SS132
1SS254	Si-Di	=1SS133	31a	Rhm	→1SS133
1SS26	Ge-Di	Dem, 40V, 50mA	31a	Unz	AA113, 1N34, 1N54, 1N60
1SS265	Si-Di	=1SS135	31a	Rhm	→1SS135
1SS268	Si-Di	SMD, Dual, VHF-Band-S, 30V, <0,8Ω	35f	Tos	—
1SS269	Si-Di	=1SS268:	35n		—
1SS27	Ge-Di	Dem, 40V, 50mA	31a	Unz	AA113, 1N34, 1N54, 1N60
1SS270	Si-Di	Dem, SS, 30V, 0,15A, <3,5ns	31a	Hit	BA221, BAY74, 1N4148..49, 1N4154,++
1SS270A	Si-Di	=1SS270: 70V	31a		BAW82, BAX95, 1N4148..49, 1N4151,++
1SS271	Si-Di	SMD, Schottky, Dual, VHF/UHF, 6V, 30mA	35t	Tos	—
1SS272	Si-Di	SMD, Dual, SS, 85V, 0,1A, <4ns	44(AAKK)	Tos	—
1SS276	Si-Di	Schottky-Di, Tuner-M, 3V, 30mA	31a	Hit	BA460..481, BAR19, BAT29
1SS277	C-Di	VHF/UHF-Band-S, 35V, 0,1A, <0,5Ω	31a	Hit	BA282, BA284, BA482
1SS279	C-Di	VHF/UHF-Band-S, 35V, 0,1A, <1Ω	31a	Nec	BA244, BA282, BA284, BA482
1SS28	Ge-Di	Dem, 30V, 50mA	31a	Unz	AA113, 1N34, 1N54, 1N60
1SS280	C-Di	VHF/UHF-Band-S, 35V, 0,1A, <0,6Ω	31a	Nec	BA244, BA282, BA284, BA482
1SS281	Si-Di	Schottky, UHF-M, 10V, 85mA, <1pF(0V)	31a	Nec	BAT19, BAT45, 1SS+F982288, 1SS106
1SS282	Si-Di	Schottky, UHF-M, 5V, 50mA, <1pF(0V)	31a	Nec	1S1925
1SS283	Si-Di	Schottky, UHF-M, 5V, 30mA, <0,8pF(0V)	31a	Nec	BAR10, BAT45, 1N5712
1SS285	Si-Di	Schottky, UHF-M, 70V, 15mA, <2pF(0V)	31a	Nec	HSS102
1SS286	Si-Di	Schottky-Di, Dem, S, 25V, 35mA	31a	Hit	BAT81, HSS101, 1S1992, 1SS106
1SS287	Si			Tos	—
1SS288	Si			Tos	—
1SS289	Si			Tos	—
1SS29	Ge-Di	Dem, 40V, 50mA	31a	Unz	AA113, 1N34, 1N54, 1N60
1SS290	Si-Di	=1SS139	31a	Rhm	→1SS139
1SS291	Si-Di	=1SS140	31a	Rhm	→1SS140
1SS292	Si-Di	=1SS141	31a	Rhm	→1SS141
1SS293	Si-Di	Schottky-Di, S, 45V, 0,1A	41g	Tos	BAT86
1SS294	Si-Di	=1SS293: SMD	35p		1SS348
1SS295	Si-Di	SMD, Schottky, Dual, UHF-M, 4V, 0,05A	35t	Tos	—
1SS30	Ge-Di	Dem, 75V, 50mA	31a	Unz	—
1SS300	Si-Di	=1SS181:	35n(2mm)	Tos	—
1SS301	Si-Di	=1SS184:	35f(2mm)	Tos	—
1SS302	Si-Di	=1SS226:	35t(2mm)	Tos	—
1SS306	Si-Di	SMD, Dual, S, 250V, 0,1A, <60ns	44(AAKK)	Tos	—
1SS307	Si-Di	SMD, 35V, 0,1A	35p	Tos	BAS19..21, BAS29
1SS308	Si-Di	SMD, Quad, SS, 85V, 0,1A, <4ns	45	Tos	—
1SS309	Si-Di	SMD, Quad, SS, 85V, 0,1A, <4ns	45	Tos	—
1SS31	Ge-Di	Dem, 50V, 50mA	31a	Unz	AA113, 1N34, 1N54, 1N60
1SS311	Si-Di	SMD, S, 420V, 0,1A, 1,5µs	35p	Tos	—
1SS312	C-Di	=1SS286	35f(2mm)	Tos	—
1SS313	C-Di	=1SS269	35n(2mm)	Tos	—
1SS314	C-Di	=1SS241:	71a(1,7mm)	Tos	BA592, 1SS356
1SS315	C-Di	=1SS242:	71a(1,7mm)	Tos	—
1SS317	C-Di	VHF/UHF-Band-S, 35V, 0,1A, <0,6Ω	31a	Nec	BA244, BA292, BA284, BA482
1SS318	C-Di	VHF-Band-S	71a(1,7mm)	Rhm	BA582, 1SS314
1SS319	Si-Di	=1SS293: SMD, Dual	44(AAKK)	Tos	—
1SS321	Si-Di	SMD, Schottky-Di, Dual, S, 12V, 0,05A	35f	Tos	—
1SS322	Si-Di	=1SS294: SMD	35p(2mm)	Tos	—
1SS332	Si-Di	SMD, SS, 40V, 0,1A, <4ns	71a(1,7mm)	Rhm	1SS354, 1SS355
1SS336	Si-Di	SMD, Dual, S, 85V, 0,2A, <20ns	35n	Tos	—
1SS337	Si-Di	=1SS336:	35t	Tos	—
1SS344	Si-Di	SMD, Schottky-Di, S, 25V, 0,5A, 20ns	35p	Tos	1SS349
1SS345	Si-Di	SMD, Schottky-Di, UHF-M, 55V, 10mA	35p	Say	—
1SS348	Si-Di	SMD, Schottky-Di, S, 85V, 0,1A	35p	Tos	—
1SS349	Si-Di	SMD, Schottky-Di, S, 25V, 1A	35p	Tos	—

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1SS350	Si-Di	SMD, Schottky-Di, UHF-M, 5V, 30mA	35p	Say	BAT17
1SS351	Si-Di	=1SS350: Dual	35t	Say	—
1SS352	Si-Di	SMD, SS, 85V, 0,1A, <4ns	71a(1,7mm)	Tos	1SS353
1SS353	Si-Di	SMD, SS, 90V, 0,1A, <4ns	71a(1,7mm)	Rhm	1SS352
1SS354	Si-Di	SMD, SS, 50V, 0,1A, <4ns	71a(1,7mm)	Rhm	1SS352
1SS355	Si-Di	SMD, SS, 40V, 0,1A, <4ns	71a(1,7mm)	Rhm	1SS332, 1SS352
1SS356	C-Di	HF-Band-S, 30V, 0,1A, <1,2pF, <0,9Ω	71a(1,7mm)	Rhm	BA592, 1SS314
1SS357	Si-Di	=1SS293: SMD	71a(1,7mm)	Tos	—
1SS358	Si-Di	=1SS345: Dual	35t	Say	—
1SS360	Si-Di	=1SS181:	35n(1,6mm)	Tos	—
1SS361	Si-Di	=1SS184:	35f(1,6mm)	Tos	—
1SS362	Si-Di	=1SS184:	35t(1,6mm)	Tos	—
1SS364	Si-Di	=1SS268:	35f(1,6mm)	Tos	—
1SS365	Si-Di	SMD, Schottky-Di, 10V, 35mA, 0,85pF	35p	Say	MA704
1SS366	Si-Di	=1SS365: Dual	35t	Say	—
1SS367	Si-Di	SMD, Schottky-Di, S, 15V, 0,1A	71a(1,7mm)	Tos	—
1SS368	Si-Di	=1SS352:	71a(1,3mm)	Tos	—
1SS369	Si-Di	=1SS357:	71a(1,3mm)	Tos	—
1SS370	Si-Di	=1SS250:	35p(2mm)	Tos	—
1SS371	Si-Di	=1SS241:	71a(1,3mm)	Tos	—
1SS372	Si-Di	=1SS367: Dual	35t(2mm)	Tos	—
1SS373	Si-Di	=1SS367:	71a(1,3mm)	Tos	—
1SS374	Si-Di	=1SS367: Dual	35t(3mm)	Tos	—
1SS375	Si-Di	=1SS365: Dual	35t(2mm)	Say	—
1SS377	Si-Di	=1SS367: Dual	35f(3mm)	Tos	—
1SS378	Si-Di	=1SS367: Dual	35f(2mm)	Tos	—
1SS379	Si-Di	=1SS367: Dual	35t(3mm)	Tos	—
1SS382	Si-Di	SMD, Dual, SS, 80V, 0,1A, 1,6ns	44(2mm)	Tos	—
1SS362	Si-Di	SMD, SS, 80V, 0,1A, 1,6ns	71a(1,3mm)	Tos	—
1SS383	Si-Di	SMD, Schottky, Dual, 40V, 0,1A	44(2mm)	Tos	—
1SS364	Si-Di	SMD, Schottky, Dual, 10V, 0,1A	44(2mm)	Tos	—
1SS385	Si-Di	SMD, Schottky, Dual, 10V, 0,1A	35f(1,6mm)	Tos	—
1SS388	Si-Di	SMD, Schottky, 40V, 0,1A	71a(1,3mm)	Tos	—
1SS389	Si-Di	SMD, Schottky, 10V, 0,1A	71a(1,3mm)	Tos	—
1SS41	Si-Di	SS, 100V, 0,13A, <4ns	31a	Rhm	BA219, 1N4148..49, 1N4446..49
1SS42	Si-Di	Schottky-Di, UHF-M, 5V, 30mA, 900MHz	31a	Tos	BA480..481, BAR19, BAT29
1SS43	Si-Di	Schottky-Di, Modulator, 5V, 30mA	31a	Nec	BA480..481, BAR19, BAT29
1SS46	Si-Di	Dual, 70V, 0,1A	5	Fui	—
1SS49	Si-Di	SS, 35V, 0,1A, <10ns	31a	Mat	BAY69, BAY71, 1N4148..49, 1N4446..49++
1SS50	Si-Di	SS, 50V, 0,1A, <4ns	31a	Mat	BA318, BAY36, 1N4148..49, 1N4446..49++
1SS51	Si-Di	SS, 75V, 0,1A, <10ns	31a	Mat	BAW62, BAX95, 1N4148..49, 1N4446..49++
1SS52	Si-Di	SS, 35V, 0,1A, <3ns		Nec	BA318, BAY38, 1N4146..49, 1N4446..49++
1SS53	Si-Di	S, 35V, 0,1A, <100ns	31a	Nec	BAX90, BAX94, BAY41..43, 1N4148..49++
1SS54	Si-Di	=1SS53: 75V	31a	Nec	BAW49, BAY43, BAY72, 1N4148..49, ++
1SS55	Si-Di	=1SS53: 100V	31a	Nec	BAW49, BAX12, BAY72, 1N4148..49, ++
1SS68	Si-Di	SS, 40V, 45mA, <6ns	31a	Fui	—
1SS69	Si-Di	Schottky-Di, UHF-Dem/M, 4V, 9375MHz	Koax	Nec	BA480..461, BAR19, BAT29
1SS70	Si-Di	Schottky-Di, UHF-M, 4V, 30mA, 9375MHz	Koax	Nec	BA480..461, BAR19, BAT29
1SS78	Si-Di	Schottky-Di, UHF-Dem/M, 5V, 9375MHz	31a	Nec	BA480..481, BAR19, BAT29
1SS81	Si-Di	S, 200V, 0,2A, <100ns	31a	Hit	BA197..198, BAV20..21, BAW50
1SS82	Si-Di	=1SS81: 250V	31a		BA198, BAV21
1SS83	Si-Di	=1SS81: 300V	31a		—
1SS84	Si-Di	S, 75V, 0,15A, <50ns	31a	Hit	BAV19..21, BAW49, BAY43, BAY72, ++
1SS85	C-Di	VHF-Band-S	31a	Hit	BA182, BA243, BA283, BA483..484, ++
1SS86	Si-Di	Schottky-Di, TV, UHF-M, 3V, 30mA	31a	Hit	—
1SS87	Si-Di	Schottky-Di, TV, UHF-M, 3V, 15mA	31a	Hit	—
1SS86	Si-Di	Schottky-Di, UHF-M, CATV, 10V, 15mA	31a	Hit	BAT19, 1SS106
1SS90	Si-Di	Schottky-Di, UHF-M, 5V, 30mA	31a	Hit	BA480..461, BAR19, BAT29
1SS91(-G,-S)	C-Di	VHF-Band-S	31a	Njr	BA182, BA243, BA283, BA483..464, ++
1SS92	Si-Di	SS, 75V, 0,2A, <2ns	31a	Rhm	BAW62, BAX95, 1N4148..49, 1N4446..49++
1SS93	Si-Di	=1SS92: 55V	31a	Rhm	BAW62, BAX95, 1N4148..49, 1N4448..49++
1SS94	Si-Di	=1SS92: 40V	31a	Rhm	BAW62, BAY95, 1N4146..49, 1N4446..49++
1SS97(1,2)	Si-Di	Schottky-Di, 10..30V, 35mA	31a	Nec	HSS100..102
1SS98	Si-Di	Schottky-Di, 5V, 50mA	31a	Nec	1S1925
1SS99	Si-Di	Schottky-Di, 5V	31a	Nec	—

1SV...1SZ .... 1SV..1SZ

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1SV100	C-Di	AM-Tuning	41d	Tos	BB112, BB130, BB509, 1SV134..135, ++
1SV101	C-Di	VHF-AFC, FM-Tuner	41d	Tos	BA125, BB119, 1SV114, 1SV125
1SV102	C-Di	HiFi-AM-Tuning, 360..450pF(2V)	41d	Tos	BB112, BB130, BB509, 1SV134..135, ++
1SV103	C-Di	Dual, FM-Tuning	41j	Tos	BB104, BB204, BB304, MV104, 1SV109
1SV104	C-Di	Dual, FM-Tuning	7a	Njr	BB104, BB204, BB304, MV104, 1SV109
1SV109	C-Di	Dual, FM-Tuning	7e	Hit	BB104, BB204, BB304, MV104, 1SV55
1SV110	C-Di	VHF-Tuning	31a	Hit	BB105, BB205, BB305, BB405, BB505++
1SV111	C-Di	UHF-Tuning	31a	Hit	BB105, BB205, BB305, BB405, BB505++
1SV112	C-Di	VHF-Tuning	31a	Hit	BB105, BB205, BB305, BB405, BB505++
1SV113	C-Di	VHF-Tuning	31a	Hit	BB105, BB205, BB305, BB405, BB505++
1SV114	C-Di	TV/FM-Tuner-AFC	31a	Hit	BB119, 1SV50, 1SV114, 1SV125
1SV115	C-Di	AM-Tuning	7d	Hit	BB112, BB130, BB509, 1SV134..135, ++
1SV116	C-Di	AM-Tuning	7d	Hit	BB112, BB130, BB509, 1SV134..135, ++
1SV118	C-Di	AM-Tuning	7d	Nec	BB112, BB130, BB509, 1SV134..135, ++
1SV12	Si-Di	UHF-Multipl., 45V, 10GHz	Koax	Njr	—
1SV121	PIN-Di	HF-Abschw./attenuator, 100V, 0,1A	31a	Hit	—
1SV122	PIN-Di		Koax	Nec	—
1SV123	C-Di	UHF-Tuning	71a(4mm)	Tos	BB105, BB205, BB305, BB405, BB505++
1SV124	C-Di	VHF-Tuning	31a	Hit	BB105, BB205, BB305, BB405, BB505++
1SV125	C-Di	VHF/UHF-AFC	31a	Hit	BA125, BB119, 1SV114
1SV126	C-Di	FM/VHF-Tuning	31a	Hit	BB109, BB143, BBY30, MV109, 1SV50, ++
1SV126	PIN-Di	SMD, VHF/UHF, AGC, 50V, 0,05A, 0,25pF	35p	Tos	—
1SV129	C-Di	AM-Tuning	33a	Njr	BB112, BB130, BB509, 1SV134..135, ++
1SV13	Si-Di	UHF-Multipl., 45V, 10GHz	Koax	Njr	—
1SV132	C-Di	UHF-Tuning	31a	Hit	BB105, BB205, BB305, BB405, BB505++
1SV133	C-Di	VHF-Tuning	31a	Hit	BB105, BB205, BB305, BB405, BB505++
1SV134	C-Di	AM-Tuning	31a	Hit	BB112, BB130, BB509, 1SV102, 1SV129++
1SV135	C-Di	AM-Tuning	31a	Hit	BB112, BB130, BB509, 1SV102, 1SV129++
1SV136	C-Di	VHF/UHF-Tuning	31a	Hit	BB105, BB205, BB305, BB405, BB505++
1SV136	C-Di	CATV-Tuning	~71a(4mm)	Tos	MA337, MA338, MA353
1SV14	Si-Di	UHF-Multipl., 45V, 10GHz	Koax	Njr	—
1SV145	C-Di	TV-Tuner, VHF/UHF-AFC, 34V	31a	Hit	BB119, 1SV114, 1SV126
1SV146	C-Di	TV-Tuner, VHF/UHF-AFC, 34V	31a	Hit	BB119, 1SV114, 1SV125
1SV147	C-Di	Dual, FM-Tuning	41e	Tos	BB104, BB204, BB304, MV104, 1SV109
1SV148	C-Di	UHF-Tuning	71a(4mm)	Rhm	BB105, BB205, BB305, BB405, BB505++
1SV149	C-Di	AM-Tuning	41d	Tos	BB509, MV1401..1404, 1SV134..135, ++
1SV15	Si-Di	UHF-Multipl., 45V, 10GHz	Koax	Njr	—
1SV151	C-Di	FM/VHF-Tuner-AFC	31a	Hit	BB119, 1SV114, 1SV125, 1SV145..146
1SV153(A)	C-Di	SMD, TV, VHF/UHF-Tuning	71a(2,7mm)	Tos	BB515, BB721, BB723, BB729..731
1SV154	PIN-Di	HF-S, 65V, 0,1A	31a	Hit	—
1SV155	C-Di	VHF-Tuning	31a	Hit	BB205, BB305, BB405, BB505, 1SV124++
1SV156	PIN-Di	HF-Abschw./Atten., 30V, 0,05A, <0,6pF	31a	Nec	—
1SV157	PIN-Di	HF-Abschw./Atten., 50V, 0,05A, <0,9pF	31a	Nec	1SV196
1SV16	Si-Di	UHF-Multipl., 60V, 10GHz	Koax	Njr	—
1SV160	C-Di	SMD, FM-AFC, 15V, 7..14pF	35c	Tos	—
1SV161	C-Di	SMD, CATV-Tuning	71a(2,7mm)	Tos	BB721, BB723, BB729..731
1SV163	C-Di	VHF/UHF-AFC, 30V, 11..17pF(2V)	31a	Nec	BB117, BB417
1SV164	C-Di	VHF/UHF-Tuning, 30V, 11..12,7pF(3V)	31a	Nec	BB405, BB505, 1SV111, 1SV146
1SV165	C-Di	VHF/UHF-Tuning, 30V, 10,3..13pF(3V)	31a	Nec	BB405, BB505, 1SV111, 1SV148
1SV166	C-Di	FM/VHF-Tuning, 30V, 28..32,5pF(3V)	31a	Nec	BB109, BB143, BBY30, MV109, 1SV50
1SV166(1)	C-Di	FM/VHF-Tuning, 30V, 29..34pF(3V)	31a	Nec	BB109, BB143, BBY30, MV109, 1SV50
1SV166S	C-Di	VHF-VCO, 30V, 23..36pF(3V)	31a	Nec	—
1SV167	C-Di	VHF/CATV-Tuning, 30V, 26..32pF(3V)	31a	Nec	1SV209
1SV169	C-Di	VHF/UHF-Tuning, 30V, 2,1..2,5pF(2V)	31a	Nec	BB405, BB505, 1SV111, 1SV148
1SV17	Si-Di	UHF-Multipl., 60V, 10GHz	Koax	Njr	—
1SV170	C-Di	VHF/UHF-AFC, 30V, 13,7..17pF(2V)	31a	Nec	BB117, BB417
1SV172	C-Di	SMD, Dual, VHF/UHF-Band, AGC	35t	Tos	—
1SV176	PIN-Di	Antenn.-S, 65V, 0,15A	31a	Hit	—
1SV18	Si-Di	UHF-Multipl., 60V, 10GHz	Koax	Njr	—
1SV163	C-Di	UHF-Tuning, VCD, 28V, 2..4pF(2V)	31a	Nec	1SV210
1SV164	C-Di	FM/VHF-Tuning, VCO, 15V, 40..50pF(2V)	31a	Nec	BB109, BB143, BBY30, MV109, 1SV213
1SV166	C-Di	UHF/SHF-Tuning, 3,3..4,5pF(2V)	71a(2,7mm)	Tos	—
1SV187	PIN-Di	Antenn.-S, HF-Abschw., 60V, 0,05A	31a	Hit	—
1SV188	C-Di	VHF/UHF-Tuning	71a(2,7mm)	Hit	BB721, BB723, BB729..731
1SV19	Si-Di	UHF-Multipl., 60V, 10GHz	Koax	Njr	—

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1SV191	C-Di	VHF/CATV-Tuning, 30V, 32..37pF(2V)	31a	Nec	1SV167, 1SV209
1SV193	C-Di	VHF/UHF-Tuning	71a(2,7mm)	Hit	BB721, BB723, BB729..731
1SV194	C-Di	VHF-Tuning	71a(2,7mm)	Hit	BB419, BB619..620
1SV196	PIN-Di	HF-Abschw./Atten., 50V, 0,05A, <0,9pF	31a	Nec	1SV157
1SV20	Si-Di	UHF-Multipl., 60V, 10GHz	Koax	Njr	—
1SV200	C-Di	VHF-Tuning	71a(2,7mm)	Hit	BB419, BB619..620
1SV202	C-Di	UHF-Tuning	71a(2,7mm)	Hit	BB721, BB723, BB729..731
1SV203	C-Di	VHF-Tuning	71a(2,7mm)	Hit	BB419, BB619..620
1SV204	C-Di	VHF/UHF-AFC, 10,5..16pF(2V)	71a(2,7mm)	Tos	—
1SV205	C-Di	Tuning, 35V	71a(2,7mm)	Rhm	BB721, BB723, BB729..31, 1SV202
1SV207	C-Di	VHF/UHF, 30V, 30..33pF(2V)	31a	Rhm	—
1SV209	C-Di	VHF/CATV-Tuning, 30V, 26,6..32pF(2V)	31a	Nec	1SV167
1SV21	Si-Di	Varaktor, 45V	Koax	Njr	—
1SV210	C-Di	VHF/UHF-Tuning, VCO, 26V, 2..4pF(2V)	31a	Nec	1SV183
1SV211	C-Di	UHF-CATV-Tuning, 33..39pF(2V)	71a(2,7mm)	Tos	—
1SV212	C-Di	UHF-VCO, 14..16pF(2V)	71a(2,7mm)	Tos	—
1SV213	C-Di	FM/VHF-Tuning, VCO, 15V, 35..41pF(2V)	31a	Nec	BB109, BB143, BBY30, MV109, 1SV184
1SV214	C-Di	=1SV153A:	71a(1,7mm)	Tos	—
1SV215	C-Di	=1SV161:	71a(1,7mm)	Tos	—
1SV216	C-Di	=1SV204:	71a(1,7mm)	Tos	—
1SV217	C-Di	=1SV211:	71a(1,7mm)	Tos	—
1SV218	C-Di	VHF/CATV-Tuning, 30V, 32..37pF(2V)	71a	Nec	—
1SV219	C-Di	VHF/CATV-Tuning, 30V, 26,6..32pF(2V)	71a	Nec	—
1SV22	Si-Di	Varaktor, 45V	Koax	Njr	—
1SV220	C-Di	VHF/UHF-Tuning, VCO, 30V, 9,5..14pF(2V)	71a	Nec	BB515, BB721, BB723
1SV221	C-Di	VHF/UHF-Tuning, VCO, 30V, 14..16,4pF(2V)	71a	Nec	BB515, BB721, BB723
1SV222	C-Di	VHF/UHF-Tuning, VCO, 30V, 13,7..17pF(2V)	71a	Nec	—
1SV223	C-Di	=1SV205:	71a(1,7mm)	Rhm	BB535, BB621..623, 1SV214
1SV224	C-Di	CATV-O, Converter	71a(2,7mm)	Tos	—
1SV225	C-Di	SMD, Dual, FM-Tuning	35f	Tos	—
1SV226	C-Di	UHF-CATV-Tuning	71a(2,7mm)	Tos	—
1SV227	C-Di	UHF-CATV-Tuning	71a(2,7mm)	Tos	—
1SV228	C-Di	SMD, Dual, FM-Tuning	35f	Tos	—
1SV229	C-Di	=1SV212:	71a(1,7mm)	Tos	—
1SV23	Si-Di	Varaktor, 90V	Koax	Njr	—
1SV230	C-Di	=1SV224:	71a(1,7mm)	Tos	—
1SV231	C-Di	=1SV226:	71a(1,7mm)	Tos	—
1SV232	C-Di	=1SV227:	71a(1,7mm)	Tos	—
1SV233	PIN-Di	SMD, VHF/UHF-AGC, 50V, 0,05A	35p	Say	—
1SV234	PIN-Di	=1SV233: Dual	35l	Say	—
1SV237	C-Di	SMD, Dual, VHF/UHF-Band, AGC	44(AAKK)	Tos	—
1SV238	C-Di	SMD, UHF-CATV-Tuning	71a(1,7mm)	Tos	—
1SV239	C-Di	SMD, UHF-VCO	71a(1,7mm)	Tos	—
1SV24	Si-Di	Varaktor, 90V	Koax	Njr	—
1SV241	PIN-Di	VHF/UHF, 50V, 0,23pF	45	Say	—
1SV242	C-Di	SMD, Dual, VHF/UHF-Tuning, 36..42pF	35f	Tos	—
1SV242(SM)	C-Di	=1SV242:	71a(2,7mm)		—
1SV245	C-Di	SMD, UHF/SHF-Tuning	71a(1,7mm)	Tos	—
1SV246	PIN-Di	=1SV233: Dual	35t(2mm)	Say	—
1SV247	PIN-Di	=1SV233:	35p(2mm)	Say	—
1SV248	PIN-Di	=1SV250:	35(2mm)	Say	—
1SV249	PIN-Di	=1SV251:	35(2mm)	Say	—
1SV250	PIN-Di	SMD, VHF/UHF, 50V, 0,23pF	35(2,9mm)	Say	—
1SV251	PIN-Di	=1SV250: Dual	35(2,9mm)	Say	—
1SV252	C-Di	=1SV172:	35t(2mm)	Tos	—
1SV254	C-Di	=1SV153A:	71a(1,3mm)	Tos	—
1SV255	C-Di	=1SV161:	71a(1,3mm)	Tos	—
1SV256	C-Di	=1SV204:	71a(1,3mm)	Tos	—
1SV257	C-Di	=1SV212:	71a(1,3mm)	Tos	—
1SV258	C-Di	=1SV224:	71a(1,3mm)	Tos	—
1SV259	C-Di	=1SV227:	71a(1,3mm)	Tos	—
1SV26	PIN-Di	110V, 0,05A, 1,7GHz		Nec	—
1SV260	C-Di	=1SV239:	71a(1,3mm)	Tos	—
1SV261	C-Di	=1SV245:	71a(1,3mm)	Tos	—
1SV262	C-Di	SMD, UHF-CATV-Tuning, 33..36pF(2V)	71a(1,7mm)	Tos	—
1SV263	PIN-Di	=1SV266:	35(2mm)	Say	—

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1SV264	PIN-Di	=1SV267:	35(2mm)	Say	—
1SV265	PIN-Di	SMD, VHF/UHF, 50V, 0,23pF	45	Say	—
1SV266	PIN-Di	SMD, VHF/UHF, 50V, 0,23pF	35(2,9mm)	Say	—
1SV267	PIN-Di	=1SV266: Dual	35(2,9mm)	Say	—
1SV268	PIN-Di	SMD, VHF/UHF, 50V, 0,7pF	39	Say	—
1SV269	C-Di	SMD, UHF-CATV-Tuning, 29..34pF(2V)	71a(1,7mm)	Tos	—
1SV27	PIN-Di	110V, 0,05A, 1,7GHz	Koax	Nec	—
1SV270	C-Di	SMD, UHF VCO, 15..17pF(1V)	71a(1,7mm)	Tos	—
1SV271	C-Di	=1SV237:	71a(1,7mm)	Tos	—
1SV272	PIN-Di	SMD, VHF/UHF, 50V, 0,6pF	35(2,9mm)	Say	—
1SV273	C-Di	=1SV270:	71a(1,7mm)	Tos	—
1SV274	C-Di	=1SV262:	71a(1,3mm)	Tos	—
1SV275	C-Di	=1SV269:	71a(1,3mm)	Tos	—
1SV276	C-Di	=1SV270:	71a(1,7mm)	Tos	—
1SV277	C-Di	VHF/UHF-Tuning, 10V, 4..4,9(1V)	71a(1,7mm)	Tos	—
1SV278	C-Di	=1SV153A:	71a(1,3mm)	Tos	—
1SV279	C-Di	=1SV212:	71a(1,3mm)	Tos	—
1SV28	PIN-Di	110V, 0,05A, 1,7GHz		Nec	—
1SV280	C-Di	=1SV239:	71a(1,3mm)	Tos	—
1SV281	C-Di	=1SV270:	71a(1,3mm)	Tos	—
1SV282	C-Di	=1SV262:	71a(1,3mm)	Tos	—
1SV283	C-Di	=1SV269:	71a(1,3mm)	Tos	—
1SV284	C-Di	=1SV270:	71a(1,3mm)	Tos	—
1SV285	C-Di	=1SV277:	71a(1,3mm)	Tos	—
1SV286	C-Di	=1SV224:	71a(1,3mm)	Tos	—
1SV29	Si-Di	UHF-Multipl., 32V, 11GHz		Nec	—
1SV294	PIN-Di	SMD, VHF/UHF, 50V, 0,23pF	35(2,9mm)	Say	—
1SV298	PIN-Di	SMD, VHF/UHF, 50V, 0,23pF	44	Say	—
1SV30	Si-Di	UHF-Multipl., 48V, 11GHz	Koax	Nec	—
1SV31	Si-Di	UHF-Multipl., 48V, 11GHz	Koax	Nec	—
1SV32	Si-Di	UHF-L, 90V, 350..650MHz	32a	Nec	—
1SV33	Si-Di	UHF-L, 90V, 250..550MHz	32a	Nec	—
1SV34	PIN-Di	110V, 0,05A, 10GHz	31a	Nec	—
1SV35	PIN-Di	110V, 0,05A, 10GHz	31a	Nec	—
1SV36	PIN-Di	110V, 0,05A, 10GHz		Nec	—
1SV37	PIN-Di	110V, 0,05A, 10GHz	Koax	Nec	—
1SV45	Si-Di	Snap-off-Di, UHF-Multipl.	Koax	Nec	—
1SV46	PIN-Di	S, 65V, <120ns		Nec	—
1SV47	PIN-Di	S, 65V, <120ns	Koax	Nec	—
1SV48	PIN-Di	Modulator, S	Koax	Nec	—
1SV49	GaAs-Di	UHF-Multipl., 20V, 18GHz		Nec	—
1SV50(-1,S)	C-Di	FM/VHF-AFC/Tuning	71a(4mm)	Nec	BB109, BB143, MV109, MV2101..2115
1SV52	GaAs-Di	Schottky-Di		Nec	—
1SV53(A,B)	C-Di	VHF-AFC	31a	Njr	BA125, BB119, 1SV114, 1SV125
1SV54(G)	C-Di	VHF-AFC	71a(4mm)	Nir	BA125, BB119, 1SV114, 1SV125
1SV55	C-Di	Dual, FM-Tuning	7e	Hit	BB104, BB204, BB304, MV104, 1SV109
1SV56	C-Di	SMD, VHF-AFC/Tuning		Nec	—
1SV57	C-Di	SMD, VHF-AFC/Tuning		Nec	
1SV56	C-Di	VHF-Tuning	71a(4mm)	Hit	BB105, BB205, BB305, BB405, BB505++
1SV59	C-Di	VHF-Tuning	71a(4mm)	Hit	BB105, BB205, BB305, BB405, BB505++
1SV65	PIN-Di	S, Modulator, 33V, <60ns	Koax	Nec	—
1SV66	PIN-Di	S, Modulator, 33V, <60ns	Koax	Nec	—
1SV68	C-Di	FM-Tuning	31a	Hit	BB101, BB110, BB203, MV310, 1SV84
1SV69	C-Di	VHF-Tuning	31a	Hit	BB105, BB205, BB305, BB405, BB505++
1SV70	C-Di	UHF-Tuning	31a	Hit	BB105, BB205, BB305, BB405, BB505++
1SV71	C-Di	AFC	31a	Njr	—
1SV72	C-Di	AFC	31a	Njr	—
1SV73	C-Di	AFC	31a	Njr	—
1SV74	C-Di	AFC	31a	Njr	—
1SV75	C-Di	VHF-AFC/Tuning	71a(4mm)	Tos	BB105, BB205, BB305, BB405, BB505++
1SV76	C-Di	VHF-AFC/Tuning	71a(4mm)	Njr	BB105, BB205, BB305, BB405, BB505++
1SV77	PIN-Di	VHF, S, 70V, <800ns	7d	Nec	—
1SV60	PIN-Di	VHF, 30V	31a	Nec	—
1SV81	Si-Di	VHF/UHF TV-Tuner		Tos	—
1SV82	PIN-Di	0,25pF(50V)		Tos	—
1SV84	C-Di	FM-Tuning	31a	Hit	BB101, BB110, BB203, MV310, 1SV68

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1SV87	C-Di	VHF-Tuning	31a	Hit	BB105, BB205, BB305, BB405, BB505++
1SV88	C-Di	VHF-Tuning	71a(4mm)	Nip	BB105, BB205, BB305, BB405, BB505++
1SV89	C-Di	UHF-AFC	31a	Hit	BA121, BB117, BB417
1SV90(A)	C-Di	AM-Tuning	7d	Hit	BB112, BB130, BB509, 1SV134..135, ++
1SV91	C-Di	AM-Tuning	7d	Hit	BB112, BB130, BB509, 1SV134..135, ++
1SV92	C-Di	AM-Tuning	7d	Hit	BB112, BB130, BB509, 1SV134..135, ++
1SV93	C-Di	AM-Tuning	7d	Hit	BB112, BB130, BB509, 1SV134..135, ++
1SV94	C-Di	UHF-Tuning	31a	Hit	BB105, BB205, BB305, BB405, BB505++
1SV95	C-Di	VHF-Tuning	31a	Hit	BB105, BB205, BB305, BB405, BB505++
1SV96	C-Di	Dual	7c	Hit	—
1SV97	C-Di	VHF-Tuning	31a	Hit	BB105, BB205, BB305, BB405, BB505++
1SV98	C-Di	TV/FM-Tuner-AFC	31a	Hit	BB119, 1SV50, 1SV114, 1SV125
1SV99	PIN-Di	Band-S, 50V, 0,05A, 0,3pF, 7Ω	7d	Tos	—
1SX170	Si-Di	GI, S, TV, 60V, 1,5A, <350ns		Tix	BY258/100, BY296..299, RGP15B,++
1SX171	Si-Di	=1SX170: 75V			BY258/100, BY298..299, RGP15B,++
1SX172	Si-Di	=1SX170: 100V			BY258/100, BY296..299, RGP15B,++
1SX173	Si-Di	=1SX170: 200V			BY258/200, BY296..299, RGP15D,++
1SX174	Si-Di	=1SX170: 300V			BY258/400, BY297..299, RGP15G,++
1SX175	Si-Di	=1SX170: 400V			BY258/400, BY298..299, RGP15G,++
1SZ45A	Ref-Di	6,4V, 5%, 0,25W, ±0,01%/°C	31a	Nec	BZV10, BZV27, BZX90, 1N4575, 1N4580++
1SZ46A	Ref-Di	6,4V, 5%, 0,25W, ±0,005%/°C	31a	Nec	BZV11, BZV28, BZX91, 1N4576, 1N4581++
1SZ47(A)	Ref-Di	6,4V, 5%, 0,25W, ±0,002%/°C	31a	Nec	BZV12, BZV29, BZX92, 1N4577, 1N4582++
1SZ48(A)	Ref-Di	6,4V, 5%, 0,25W, ±0,001%/°C	31a	Nec	BZV13, BZV30, BZX93, 1N4578, 1N4583++
1SZ50	Ref-Di	6,2V, 5%, 0,25W, ±0,01%/°C	31a	Nec	BZV10, BZV27, BZX90, 1N4575, 1N4580++
1SZ51	Ref-Di	6,2V, 5%, 0,25W, ±0,005%/°C	31a	Nec	BZV11, BZV28, BZX91, 1N4576, 1N4581++
1SZ52	Ref-Di	6,2V, 5%, 0,25W, ±0,002%/°C	31a	Nec	BZV12, BZV29, BZX92, 1N4577, 1N4582++
1SZ53	Ref-Di	6,2V, 5%, 0,25W, ±0,001%/°C	31a	Nec	BZV13, BZV30, BZX93, 1N4578, 1N4583++

1T...1ZT .... 1T..1ZT

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1T	Si-N	=2SC3077 (Typ-Code/Stempel/marking)	35		→2SC3077
1T	Si-N	=2SC3933 (Typ-Code/Stempel/marking)	35(2mm)		→2SC3933
1T	Si-N	=2SC4975 (Typ-Code/Stempel/marking)	≈35		→2SC4975
1T	Si-N	=MMBT3960A (Typ-Code/Stempel/marking	35		→MMBT3960A
1T1	Si-P	=MMST5101 (Typ-Code/Stempel/marking)	35		→MMST5101
1T1	Si-P	=SST5101 (Typ-Code/Stempel/marking)	35		→SST5101
1T32(A)	C-Di	SMD, VHF/UHF-Tuning, 30V	71a(2,7mm)	Son	BB515, BB721, BB723, 1SV188, 1SV202++
1T33(A)	C-Di	SMD, CATV-Tuning, 30V, 27,2..32pF(2V)	71a(2,7mm)	Son	—
1T339	Opto	CD, Photodiode	8-MDIP	Son	—
1T33C	C-Di	SMD, CATV-Tuning, 30V, 34,6..42pF(2V)	71a(2,7mm)	-	—
1T359	C-Di	SMD, Radio/TV-Tuning, 30V	71a(2,7mm)	Son	—
1T360	C-Di	=1T364:	71a(2,7mm)	Son	—
1T362	C-Di	=1T32:	71a(1,7mm)	Son	BB439, BB839, BB640
1T363	C-Di	=1T33C:	71a(1,7mm)	Son	—
1T364	C-Di	SMD, CATV-Tuning, 30V, 28..34pF(2V)	71a(1,7mm)	Son	—
1T365	C-Di	SMD, BS-Tuning, 30V, 3,3..4,5pF(2V)	71a(1,7mm)	Son	—
1T366	C-Di	SMD, TV-Tuner, 30V, 18,6pF(1V)	71a(1,7mm)	Son	—
1TH61	Si-Di	GI, Uni, 1500V, 0,3A, <6µs	31a	Tos	BY228, DM513, EM516, GP10W..Y
1TZ81	Si-Di	GI, Uni, 1500V, 1A	31a	Tos	BY228, DM513, EM516, GP10W..Y
1U	Si-N	=2SC3110 (Typ-Code/Stempel/marking)	35		→2SC3110
1U	Si-N	=2SC3934 (Typ-Code/Stempel/marking)	35(2mm)		→2SC3934
1U	Si-N	=KST2484 (Typ-Code/Stempel/marking)	35		→KST2484
1U	Si-N	=MMBT2484 (Typ-Code/Stempel/marking)	35		→MMBT2484
1V	Si-N	=2SD2441 (Typ-Code/Stempel/marking)	39		→2SD2441
1V	Si-N	=MMBT6427 (Typ-Code/Stempel/marking)	35		→MMBT6427
1V(p)	Si-N	=BF820 (Typ-Code/Stempel/marking)	35		→BF820
1VR	Si-N	=2SD1149-R (Typ-Code/Stempel/marking)	35		→2SD1149
1VR	Si-N	=2SD1824-R (Typ-Code/Stempel/marking)	35(2mm)		→2SD1824
1VS	Si-N	=2SD1149-S (Typ-Code/Stempel/marking)	35		→2SD1149
1VS	Si-N	=2SD1824-S (Typ-Code/Stempel/marking)	35(2mm)		→2SD1824
1VT	Si-N	=2SD1149-T (Typ-Code/Stempel/marking)	35		→2SD1149
1VT	Si-N	=2SD1824-T (Typ-Code/Stempel/marking)	35(2mm)		→2SD1824
1W	Si-N	=FMMT3903 (Typ-Code/Stempel/marking)	35		→FMMT3903
1W(p)	Si-P	=BF821 (Typ-Code/Stempel/marking)	35		→BF821
1X	Si-N	=2SC2645 (Typ-Code/Stempel/marking)	35		→2SC2845
1X(p)	Si-N	=BF822 (Typ-Code/Stempel/marking)	35		→BF822
1XB	Si-N	=2SC4780-B (Typ-Code/Stempel/marking)	35(2mm)		→2SC4780

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1XC	Si-N	=2SC4780-C (Typ-Code/Stempel/marking)	35(2mm)		→2SC4780
1Y	Si-N	=KST 3903 (Typ-Code/Stempel/marking)	35		→KST 3903
1Y	Si-N	=MMBT 3903 (Typ-Code/Stempel/marking)	35		→MMBT 3903
1Y	Si-N	=YTS 3903 (Typ-Code/Stempel/marking)	35		→YTS 3903
1Y(p)	Si-P	=BF 823 (Typ-Code/Stempel/marking)	35		→BF 823
1YQ	Si-N	=2SD2457-Q (Typ-Code/Stempel/marking)	39		→2SD2457
1YR	Si-N	=2SD2457-R (Typ-Code/Stempel/marking)	39		→2SD2457
1Z	Si-N	=MMBT 6517 (Typ-Code/Stempel/marking)	35		→MMBT 6517
1Z6,2..390(A)	Z-Di	Z, 6,2..390V, 10%(A=5%), 1W	31a	Tos	BZW22/.., BZX61/.., ZPY.., 1N5920..56,++
1ZB6,8..390	Z-Di	6,8..390V, 10%, 1W	31a	Tos	BZW22/.., BZX61/.., ZPY.., 1N5920..56,++
1ZC12...120(A)	Z-Di	12..120V, 10%(A=5%), 1W	31a	Tos	BZW22/.., BZX61/.., ZPY.., 1N5927..51,++
1ZF8,2..24	Z-Di	8,2..24V, 5%, 3W	31a	Fag	BZT03/.., BZV16/.., BZX70/..
1ZM100	Z-Di	=1ZM27: 100V	31l	Tos	—
1ZM180	Z-Di	=1ZM27: 180V	31l	Tos	—
1ZM27	Z-Di	Z, TAZ, 27V, 20%, 1W, bidirektional	31l	Tos	BZW06/..B, 1N6118..6137
1ZM30	Z-Di	=1ZM27: 30V	31l	Tos	—
1ZM330	Z-Di	=1ZM27: 330V	31l	Tos	—
1ZM390	Z-Di	=1ZM27: 390V	31l	Tos	—
1ZM47	Z-Di	=1ZM27: 47V	31l	Tos	—
1ZM50	Z-Di	=1ZM27: 50V	31l	Tos	—
1ZQ	Si-P	=2SA1890-Q (Typ-Code/Stempel/marking)	39		→2SA1690
1ZR	Si-P	=2SA1890-R (Typ-Code/Stempel/marking)	39		→2SA1890
1ZR	Si-N	=2SD1030-R (Typ-Code/Stempel/marking)	35		→2SD1030
1ZR	Si-N	=2SD1823-R (Typ-Code/Stempel/marking)	35(2mm)		→2SD1623
1ZR	Si-N	=2SD2345-R (Typ-Code/Stempel/marking)	35(1,6mm)		→2SD2345
1ZR	Si-N	=2SD2433-R (Typ-Code/Stempel/marking)	≈35		→2SD2433
1ZS	Si-N	=2SD1030-S (Typ-Code/Stempel/marking)	35		→2SD1030
1ZS	Si-N	=2SD1823-S (Typ-Code/Stempel/marking)	35(2mm)		→2SD1823
1ZS	Si-N	=2SD2345-S (Typ-Code/Stempel/marking)	35(1,6mm)		→2SD2345
1ZS	Si-N	=2SD2433-S (Typ-Code/Stempel/marking)	≈35		→2SD2433
1ZT	Si-N	=2SD1030-T (Typ-Code/Stempel/marking)	35		→2SD1030
1ZT	Si-N	=2SD1823-T (Typ-Code/Stempel/marking)	35(2mm)		→2SD1823
1ZT	Si-N	=2SD2345-T (Typ-Code/Stempel/marking)	35(1,6mm)		→2SD2345
1ZT	Si-N	=2SD2433-T (Typ-Code/Stempel/marking)	≈35		→2SD2433
2		**2, 1...3**			
2	C-Di	=1SV200 (Typ-Code/Stempel/marking)	71 (2,7mm)		→1SV200
2	C-Di	=HVR 100 (Typ-Code/Stempel/marking)	71 (2,7mm)		→HVR 100
2	C-Di	=HVU 200(A) (Typ-Code/Stempel/marking)	71 (1,7mm)		→HVU 200(A)
2,1St10	Se-St	2,1V, 10mA+C10101		old	—
2,6St10	Se-St	2,8V, 10mA		old	—
2.0..36..	Z-Di	SMD, 2,0..36V, 0,2W	71 (1,7mm)	Rhm	HZU..,RD..S
2.0B	Z-Di	=HZF 2.0BP (Typ-Code/Stempel/marking)	71 (5mm)		→HZF 2.0BP
2.0B	Z-Di	=HZF 2.0BP (Typ-Code/Stempel/marking)	71 (5mm)		→HZF 2.0BP
2.0C	Z-Di	=HZF 2.0CP (Typ-Code/Stempel/marking)	71 (5mm)		→HZF 2.0CP
2.2B	Z-Di	=HZF 2.2BP (Typ-Code/Stempel/marking)	71 (5mm)		→HZF 2.2BP
2.2C	Z-Di	=HZF 2.2CP (Typ-Code/Stempel/marking)	71 (5mm)		→HZF 2.2CP
2.4B	Z-Di	=HZF 2.4BP (Typ-Code/Stempel/marking)	71 (5mm)		→HZF 2.4BP
2.4C	Z-Di	=HZF 2.4CP (Typ-Code/Stempel/marking)	71 (5mm)		→HZF 2.4CP
27B	Z-Di	=HZF 2.7BP (Typ-Code/Stempel/marking)	71 (5mm)		→HZF 2.7BP
27C	Z-Di	=HZF 2.7CP (Typ-Code/Stempel/marking)	71 (5mm)		→HZF 2.7CP
20B	Z-Di	=HZF 20BP (Typ-Code/Stempel/marking)	71 (5mm)		→HZF 20BP
20C	Z-Di	=HZF 20CP (Typ-Code/Stempel/marking)	71 (5mm)		→HZF 20CP
20Y	Z-Di	=BZV 49/C20 (Typ-Code/Stempel/marking)	39		→BZV 49/C20
2221..2222(A)	Si-N	=2N2221..22(A): 0,625W	7a	Itt	→2N2221..22(A)
22B	Z-Di	=HZF 22BP (Typ-Code/Stempel/marking)	71 (5mm)		→HZF 22BP
22C	Z-Di	=HZF 22CP (Typ-Code/Stempel/marking)	71 (5mm)		→HZF 22CP
22Y	Z-Di	=BZV 49/C22 (Typ-Code/Stempel/marking)	39		→BZV 49/C22
24B	Z-Di	=HZF 24BP (Typ-Code/Stempel/marking)	71 (5mm)		→HZF 24BP
24C	Z-Di	=HZF 24CP (Typ-Code/Stempel/marking)	71 (5mm)		→HZF 24CP
24C02	EEPROM-IC	CMOS, Seriell, 256x8 Bit, I²C-Bus	8-DIP		2402.
24C04	EEPROM-IC	CMOS, Seriell, 512x8 Bit, I²C-Bus	8-DIP		2404..
24C08	EEPROM-IC	CMOS, Seriell, 1024x8 Bit, I²C-Bus	8-DIP		2403..
24C16	EEPROM-IC	CMOS, Seriell, 2048x8 Bit, I²C-Bus	8-DIP		2416..
24Y	Z-Di	=BZV 49/C24 (Typ-Code/Stempel/marking)	39		→BZV 49/C24
250, 260, 303, 453	SAW-Filter				—

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25SP-01..10	Si-Di	Dual, 50..1000V, 25A	≈70	Gie	—
27925	Si-P-Darl	≈BD902	17j	Rca	→BD902
27B	Z-Di	=HZF27BP (Typ-Code/Stempel/marking)	71 (5mm)		→HZF27BP
27C	Z-Di	=HZF27CP (Typ-Code/Stempel/marking)	71 (5mm)		→HZF27CP
27Y	Z-Di	=BZV49/C27 (Typ-Code/Stempel/marking)	39		→BZV49/C27
28	Si-N	=BFQ28 (Typ-Code/Stempel/marking)	52		→BFQ28
28025	Si-N-Darl	≈BD901	17j	Rca	→BD901
2906..2907(A)	Si-P	=2N2906..07(A): 0,625W	7a	Itt	→2N2906..07(A)
2910 [Intel]	CMOS-IC	→KT8520		Int	KT6520, TP3020
2911 [Intel]	CMOS-IC	→KT8521		Int	KT6521, TP3021
2912 [Intel]	CMOS-IC	→KT3040	16-DIC	Int	ETC5040, KT3040, M5912, TP8040, μA5912
2916 [Intel]	CMOS-IC	→KT3030, KT6554	16-DIC	Int	ETC5054, KT3030, TP3054, μA3054
2917 [Intel]	CMOS-IC	→KT3032, KT8557	16-DIC	Int	ETC5057, KT3032, TP3057, μA3057
2A	Si-P	=FMMT3906 (Typ-Code/Stempel/marking)	85		→FMMT3906
2A	Si-P	=KST3906 (Typ-Code/Stempel/marking)	35		→KST3906
2A	S-Di	=MA728 (Typ-Code/Stempel/marking)	71 (1,7mm)		→MA728
2A	Si-P	=MMBT3906 (Typ-Code/Stempel/marking)	85		→MMBT3+F10204906
2A	Si-P	=SXT3906 (Typ-Code/Stempel/marking)	39		→SXT3906
2A	Si-P	=YTS3906 (Typ-Code/Stempel/marking)	35		→YTS3906
2AC3T	Triac	300V, 2A(Tc=70°C), Igt/Ih <40/20mA	2m	Nec	TAG200-.., T2303-.., TAG208..
2AC5T	Triac	=2AC3T: 500V	2m		TAG200-.., T2303-.., TAG208-..
2AC6T	Triac	=2AC3T: 600V	2m		TAG200-.., T2303-.., TAG208-..
2AQ	Si-N	=2SD1304-Q (Typ-Code/Stempel/marking)	35		→2SD1304
2AR	Si-N	=2SC5026-R (Typ-Code/Stempel/marking)	39		→2SC5026
2AR	Si-N	=2SD1304-R (Typ-Code/Stempel/marking)	35		→2SD1304
2AS	Si-N	=2SC5026-S (Typ-Code/Stempel/marking)	39		→2SC5026
2AS	Si-N	=2SD1304-S (Typ-Code/Stempel/marking)	35		→2SD1304
2B	Si-N	=SC849BW (Typ-Code/Stempel/marking)	35(2mm)		→BC849W
2B	Si-P	=FMMT2907 (Typ-Code/Stempel/marking)	35		→FMMT2907
2B	Si-P	=KST2907 (Typ-Code/Stempel/marking)	35		→KST2907
2B	Si-Di	=MA729 (Typ-Code/Stempel/marking)	71 (1,7mm)		→MA729
2B	Si-P	=MMBT2907 (Typ-Code/Stempel/marking)	35		→MMBT2907
2B	Si-P	=2N2907 (Typ-Code/Stempel/marking)	46		→2N2907
2B	Si-P	=YTS2907 (Typ-Code/Stempel/marking)	35		→YTS2907
2B(p,s)	Si-N	=SC649B (Typ-Code/Stempel/marking)	35		→SC649
2BP	N-FET	=2SK374-P (Typ-Code/Stempel/marking)	35		→2SK374
2BP	N-FET	=2SK663-P (Typ-Code/Stempel/marking)	35(2mm)		→2SK663
2BQ	N-FET	=2SK374-Q (Typ-Code/Stempel/marking)	35		→2SK374
2BQ	N-FET	=2SK663-Q (Typ-Code/Stempel/marking)	35(2mm)		→2SK663
2BR	N-FET	=2SK374-R (Typ-Code/Stempel/marking)	35		→2SK374
2BR	N-FET	=2SK663-R (Typ-Code/Stempel/marking)	35(2mm)		→2SK663
2BR	Si-N	=BC849BR (Typ-Code/Stempel/marking)	35		→BC649R
2BS	N-FET	=2SK374-S (Typ-Code/Stempel/marking)	35		→2SK374
2BS	N-FET	=2SK663-S (Typ-Code/Stempel/marking)	35(2mm)		→2SK663
2Bs	Si-N	=BC849BW (Typ-Code/Stempel/marking)	35(2mm)		→SC649W
2C	Si-N	=SC849CW (Typ-Code/Stempel/marking)	35(2mm)		→BC849W
2C	Si-P	=FMMT-A70 (Typ-Code/Stempel/marking)	35		→FMMT-A70
2C	Si-Di	=MA732 (Typ-Code/Stempel/marking)	71 (1,7mm)		→MA732
2C	Si-P	=MMBTA70 (Typ-Code/Stempel/marking)	35		→MMBTA70
2C(p,s)	Si-N	=BC849C (Typ-Code/Stempel/marking)	35		→BC849
2CR	Si-N	=BC849CR (Typ-Code/Stempel/marking)	35		→BC849R
2Cs	Si-N	=BC649CW (Typ-Code/Stempel/marking)	35(2mm)		→BC849W
2D	Si-N	=BC849W (Typ-Code/Stempel/marking)	35(2mm)		→BC649W
2D	Si-P	=KST92 (Typ-Code/Stempel/marking)	35		→KST92
2D	Si-Di	=MA784 (Typ-Code/Stempel/marking)	71 (1,7mm)		→MA784
2D	Si-P	=MMBTA92 (Typ-Code/Stempel/marking)	35		→MMBTA92
2D	Si-P	=SXTA92 (Typ-Code/Stempel/marking)	39		→SXTA92
2D(p)	Si-N	=BC649 (Typ Code/Stempel/marking)	35		→BC849
2E	Si-P	=FMMT-A93 (Typ-Code/Stempel/marking)	35		→FMMT-A93
2E	Si-P	=KST93 (Typ-Code/Stempel/marking)	35		→KST93
2E	Si-Di	=MA785 (Typ-Code/Stempel/marking)	71 (1,7mm)		→MA785
2E	Si-P	=MMBTA93 (Typ-Code/Stempel/marking)	35		→MMBTA93
2E	Si-P	=SXTA93 (Typ-Code/Stempel/marking)	39		→SXTA93
2EZ3,6..200D	Z-Di	3,6..200V, 2W, D5=5%, D10=10%	31a	Sie	BZV16/.., BZV47/.., BZX70/.., ZY.., ++
2F	Si-P	=2SB1612 (Typ-Code/Stempel/marking)	39		→2SB1612
2F	Si-N	=BC850BW (Typ-Code/Stempel/marking)	35(2mm)		→BC650W

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2F	Si-P	=FMMT2907A (Typ-Code/Stempel/marking)	35		→FMMT2907A
2F	Si-P	=KST2907A (Typ-Code/Stempel/marking)	35		→KST2907A
2F	Si-P	=MMBT2907A (Typ-Code/Stempel/marking)	35		→MMBT2907A
2F	Si-P	=SXT2907A (Typ-Code/Stempel/marking)	39		→SXT2907A
2F	Si-P	=YTS2907A (Typ-Code/Stempel/marking)	35		→YTS2907A
2F(p,s)	Si-N	=BC850B (Typ-Code/Stempel/marking)	35		→BC850B
2FQ	Si-P	=2SB1583-Q (Typ-Code/Stempel/marking)	≈35		→2SB1583
2FR	Si-P	=2SB1583-R (Typ-Code/Stempel/marking)	≈35		→2SB1583
2FR	Si-P	=2SB792AR (Typ-Code/Stempel/marking)	35		→2SB792A
2FR	Si-N	=BC850BR (Typ-Code/Stempel/marking)	35		→BC850R
2FS	Si-P	=2SB1583-S (Typ-Code/Stempel/marking)	≈35		→2SB1583
2FS	Si-P	=2SB792AS (Typ-Code/Stempel/marking)	35		→2SB792A
2Fs	Si-N	=BC850BW (Typ-Code/Stempel/marking)	35(2mm)		→BC850W
2G	Si-N	=BC850C (Typ-Code/Stempel/marking)	35		→BC850
2G	Si-N	=BC850CW (Typ-Code/Stempel/marking)	35(2mm)		→BC850W
2G	Si-P	=FMMT-A56 (Typ-Code/Stempel/marking)	35		→FMMT-A56
2G	Si-P	=KST56 (Typ-Code/Stempel/marking)	35		→KST56
2G	Si-P	=MMBTA56 (Typ-Code/Stempel/marking)	35		→MMBTA56
2GM	Si-P	=MMBTA56 (Typ-Code/Stempel/marking)	35		→MMBTA56
2GR	Si-N	=BC850CR (Typ-Code/Stempel/marking)	35		→BC850R
2Gs	Si-N	=BC850CW (Typ-Code/Stempel/marking)	35(2mm)		→BC850W
2GT	Si-P	=SOA56 (Typ-Code/Stempel/marking)	35		→SOA56
2H	Si-N	=BC850W (Typ-Code/Stempel/marking)	35(2mm)		→BC850W
2H	Si-P	=FMMT-A55 (Typ-Code/Stempel/marking)	35		→FMMT-A55
2H	Si-P	=KST55 (Typ-Code/Stempel/marking)	35		→KST55
2H	Si-P	=MMBTA55 (Typ-Code/Stempel/marking)	35		→MMBTA55
2H(p)	Si-N	=BC850 (Typ-Code/Stempel/marking)	35		→BC850
2HT	Si-P	=SOA55 (Typ-Code/Stempel/marking)	35		→SOA55
2I	Si-N	=2SD2474 (Typ-Code/Stempel/marking)	89		→2SD2474
2J	Si-P	=MMBT3640 (Typ-Code/Stempel/marking)	35		→MMBT3640
2K	Si-P	=2SB1814 (Typ-Code/Stempel/marking)	39		→2SB1814
2KBP01..10	Si-Br	50..1000V, 2A	33	Gle	B30..500C2200
2L	Si-P	=KST5401 (Typ-Code/Stempel/marking)	35		→KST5401
2L	Si-P	=MMBT5401 (Typ-Code/Stempel/marking)	35		→MMBT5401
2M	Si-P	=FMMT5087 (Typ-Code/Stempel/marking)	35		→FMMT5087
2M	Si-N	=MMBT404 (Typ-Code/Stempel/marking)	35		→MMBT404

2N 2N

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2N	Si-P	=MMBT404A (Typ-Code/Stempel/marking)	35		→MMBT404A
2N100	Ge-N	NF/HF, 25V, 300mA, 0,025W	2a	Bog	(AC127, ASY28..29, 2SD30)
2N1000	Ge-N	NF/S, 40V, 0,15W, >7MHz	2a	USA	—
2N1003	Ge-P	HF, 35V, 0,12W	2a	Mot	AF124..127, AF200
2N1004	Ge-P	HF, 35V, 0,12W	2a	Mot	AF124..127, AF200
2N1005	Si-N	Uni, 15V, 0,025A, 0,15W, B>20	5e	Sty	BC168, BC183, BC236, BC548, ++
2N1006	Si-N	=2N1005: B>45	2a		BC188, BC183, BC236, BC548, ++
2N1007	Ge-P	NF-L, 40V, 3A, 30W	23a	USA	AD149, AUY19..20, 2N1529..48, ++
2N1008	Ge-P	NF/S, 20V, 0,3A, 0,2W	2a	USA, Mot	AC125..126, AC151, 2N1191..94
2N1006A	Ge-P	=2N1008: 40V	2a		ASY48, ASY77, 2N1191..94
2N1008B	Ge-P	=2N1008: 60V	2a		ASY48, ASY77
2N1009	Ge-P	NF/S, 35V, 0,3A, 0,15W	2a	USA	AC126, AC152..153
2N101(/13)	Ge-P	NF-L, 30V, 1,5A	≈37	USA	—
2N1010	Ge-N	HF, 10/10/10V, 2mA, 0,02W, 2MHz	2a	USA	—
2N1011	Ge-P	NF/S-L, 60V, 5A, 90W	23a	USA, Mot	AL102..103, AUY28, 2N3615..18, ++
2N1012	Ge-N	S, 40V, 0,15W, >3MHz	2a(B=case)	USA	—
2N1013	Ge-P	S-L, 60V		Sol	—
2N1014	Ge-P	NF/S-L, 100V, 5A, 50W	23a	USA	AL102..103, AUY26, 2N3616, 2N3618, ++
2N1015(A...F)	Si-N	NF/S-L, 30..300V, 7,5A, 150W		USA	—
2N1016(A...F)	Si-N	NF/S-L, 30..300V, 7,5A, 150W		USA	—
2N1017	Ge-P	NF, 30V, 1A, 0,2W	2a	USA	AC128, AC153, 2SB324, 2SB415
2N1018	Ge-P	NF, 30V, 1A, 0,2W	2a	USA	AC128, AC153, 2SB324, 2SB415
2N1019	-Darl	30V, 3A, 10W, B=15000		Adv	—
2N102(/13)	Ge-N	NF-L, 25V, 1,5A	≈37	USA	—
2N1020	Ge-P	45V, 7A, 10W	23a	Adv	—
2N1021(A)	Ge-P	NF/S-L, 100V, 7A, 150W	23a	USA, Mot, Tix	2N1552, 2N1556, 2N1560, 2N3616, 2N3618
2N1022(A)	Ge-P	=2N1021: 120V	23a	USA, Mot, Tix	2N2290, 2N2293
2N1023	Ge-P	HF, 40V, 10mA, 0,12W, 120MHz	4g	Cen	AF106, AF109R, AF306

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2N1024	Si-P	Uni, 18V, 0,1A, 0,25W, >1MHz	2a	USA	BC213, BC258, BC308, BC558, ++
2N1025	Si-P	Uni, 40V, 0,1A, 0,25W, >1MHz	2a	USA	BC212, BC257, BC307, BC557, ++
2N1026(A)	Si-P	Uni, 40V, 0,1A, 0,25W, >2MHz	5e	USA	BC212, BC257, BC307, BC557, ++
2N1027	Si-P	Uni, 18V, 0,1A, 0,25W, >4MHz	5e	USA	BC213, BC258, BC308, BC558, ++
2N1028	Si-P	Uni, 12V, 0,1A, 0,25W, >7,2MHz	5e	USA	BC213, BC258, BC308, BC558, ++
2N1029	Ge-P	NF/S-L, 50V, 15A, 90W, B>20	23a	USA	2N1550..52, 2N1555..58, 2N1559..60, ++
2N1029A	Ge-P	=2N1029: 60V	23a		2N1550..52, 2N1555..58, 2N1559..60, ++
2N1029B	Ge-P	=2N1029: 90V	23a		2N1552, 2N1558, 2N1560
2N1029C	Ge-P	=2N1029: 100V	23a		2N1552, 2N1556, 2N1560
2N103	Ge-N	NF, 35V, 0,01A, 0,05W	~1a	Csr,Etc	AC127, ASY28, 2SD30
2N1030	Ge-P	NF/S-L, 50V, 15A, 90W, B>60	23a	USA	2N1550..52, 2N1555..58, 2N1559..60, ++
2N1030A	Ge-P	=2N1030: 60V	23a		2N1550..52, 2N1555..58, 2N1559..60, ++
2N1030B	Ge-P	=2N1030: 90V	23a		2N1552, 2N1556, 2N1560
2N1030C	Ge-P	=2N1030: 100V	23a		2N1552, 2N1558, 2N1560
2N1031	Ge-P	NF/S-L, 50V, 15A, 90W, B>20	23a	USA	2N1550..52, 2N1555..58, 2N1559..60, ++
2N1031A	Ge-P	=2N1031: 60V	23a		2N1550..52, 2N1555..58, 2N1559..60, ++
2N1031B	Ge-P	=2N1031: 90V	23a		2N1552, 2N1558, 2N1560
2N1031C	Ge-P	=2N1031: 100V	23a		2N1552, 2N1558, 2N1560
2N1032	Ge-P	NF/S-L, 50V, 15A, 90W, B>50	23a	USA	2N1550..52, 2N1555..58, 2N1559..60, ++
2N1032A	Ge-P	=2N1032: 60V	23a		2N1550..52, 2N1555..58, 2N1559..60, ++
2N1032B	Ge-P	=2N1032: 90V	23a		2N1552, 2N1556, 2N1560
2N1032C	Ge-P	=2N1032: 100V	23a		2N1552, 2N1556, 2N1560
2N1034	Si-P	NF, 50V, 0,05A, 0,25W, β>9	5e	USA	BC212, BC257, BC307, BC557, ++
2N1035	Si-P	NF, 50V, 0,05A, 0,25W, β>18+C10407	2a	USA	BC212, BC257, BC307, BC557, ++
2N1036	Si-P	NF, 50V, 0,05A, 0,25W, β>36	2a	USA	BC212, BC257, BC307, BC557, ++
2N1037	Si-P	NF, 50V, 0,05A, 0,25W, β>9	2a	USA	BC212, BC257, BC307, BC557, ++
2N1036	Ge-P	NF/S-L, 40V, 3A, 20W(Tc=25°)	2a	USA,Mot,Tix	2N2564
2N1036-1	Ge-P	=2N1036:	2a°		2N2552, 2N2560
2N1038-2	Ge-P	=2N1036:	2a°		2N1042, 2N2558
2N1039	Ge-P	NF/S-L, 60V, 3A, 20W(Tc=25°)	2a	USA,Mot,Tix	2N2565
2N1039-1	Ge-P	=2N1039:	2e°		2N2553, 2N2561
2N1039-2	Ge-P	=2N1039:	2a°		2N1043, 2N2557
2N104	Ge-P	NF, 30V, 0,05A, 0,15W	1a	USA	AC125..128, AC151, 2SB54, 2SB56
2N1040	Ge-P	NF/S-L, 60V, 3A, 20W(Tc=25°)	2a	USA,Mot,Tix	2N2566
2N1040-1	Ge-P	=2N1040:	2a°		2N2554, 2N2562
2N1040-2	Ge-P	=2N1040:	2a°		2N1044, 2N2558
2N1041	Ge-P	NF/S-L, 100V, 3A, 20W(Tc=25°)	2a	USA,Mot,Tix	2N2567
2N1041-1	Ge-P	=2N1041:	2a°		2N2555, 2N2563
2N1041-2	Ge-P	=2N1041:	2a°		2N1045, 2N2559
2N1042	Ge-P	NF/S-L, 40V, 3,5A, 20W(Tc=25°)	2a°	USA,Mot,Tix	2N1036, 2N2558
2N1042-1	Ge-P	=2N1042:	2a°		2N2552, 2N2560
2N1042-2	Ge-P	=2N1042:	2a		2N1036, 2N2564
2N1043	Ge-P	NF/S-L, 60V, 3,5A, 20W(Tc=25°)	2a°	USA,Mot,Tix	2N1039, 2N2557
2N1043-1	Ge-P	=2N1043:	2a°		2N2553, 2N2561
2N1043-2	Ge-P	=2N1043:	2a		2N1039, 2N2565
2N1044	Ge-P	NF/S-L, 80V, 3,5A, 20W(Tc=25°)	2a°	USA,Mot,Tix	2N1040, 2N2558
2N1044-1	Ge-P	=2N1044:	2a°		2N2554, 2N2562
2N1044-2	Ge-P	=2N1044:	2a		2N1040, 2N2566
2N1045	Ge-P	NF/S-L, 100V, 3,5A, 20W(Tc=25°)	2a°	USA,Mot,Tix	2N1041, 2N2559
2N1045-1	Ge-P	=2N1045:	2a°		2N2555, 2N2563
2N1045-2	Ge-P	=2N1045:	2a		2N1041, 2N2567
2N1048	Ge-P	NF/S-L, 100V, 12A, 50W	23a	USA	2N1552, 2N1556, 2N1560
2N1046A,B	Ge-P	=2N1046: 130V	23a		AUY36, 2N2527..28
2N1047(A...C)	Si-N	NF/S-L, 60V, 8A 40W, 50MHz, B>12		USA,Tix	(MJE15028, MJE15030, 2SC3254..55)
2N1048(A...C	Si-N	=2N1047: 120V		USA,Tix	(MJE15028, MJE15030, 2SC2527)
2N1049(A...C)	Si-N	NF/S-L, 60V, 8A, 40W, 50MHz, B>30		USA,Tix	(MJE15028, MJE15030, 2SC3254..55)
2N105	Ge-P	NF, 25V, 0,015A, 0,035W	37a	USA	AC125..126, AC151, 2SB54, 2SB56
2N1050(A...C)	Si-N	=2N1049: 120V		USA,Tix	(MJE15028, MJE15030, 2SC2527)
2N1051	Si-N	NF, 60V, 0,1A, 0,5W, 3MHz	2a	SSi,Sty	BC174, BC162, BC190, BC546, ++
2N1052	Si-N	S, 160V, 0,2A, 0,6W, 4MHz	2a	USA	BF259..259, BF658..659, 2N5058..59
2N1053	Si-N	=2N1052: 200V	2a	USA	BF256..259, BF658..659, 2N5058..59
2N1054	Si-N	=2N1052: 125V	2a	USA	BF257..259, BF657..659, 2N5058..59
2N1055	Si-N	=2N1052: 100V	2e	USA	BF257..259, BF657..659, 2N5058..59
2N1056	Ge-P	NF/S, 70V, 0,3A, 0,24W	2a	USA	ASY48, ASY77, 2N2042..43
2N1057	Ge-P	NF/S, 45V, 0,3A, 0,24W	2a	USA	ASY48, ASY76..77, 2SB405ST
2N1058	Ge-N	NF/S, -/20V, 0,03A, 0,05W	2a	Etc	AC127, ASY28, ASY73..75

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2N1059	Ge-N	NF/S, 40V, 0,1A, 0,18W	≈1a	Etc	AC127, ASY28, ASY73..75
2N106	Ge-P	NF, 30V, 0,5A, 0,1W	3a	USA	AC125..126, AC151, 2SB54, 2SB56
2N1060	Si-N	S, 40V, 0,2A, 0,25W, <50/-ns	2a	Wes	BSW41, BSY63, 2N706, 2N4123,++
2N1065	Ge-P	HF/S, 40V, 0,12W, >20MHz	2a	Cen,Sty	ASY76..77
2N1068	Ge-P	HF, 40V, 10mA, 0,12W, 120MHz	5g	Cen,Phi	AF106, AF109R, AF306
2N1067	Si-N	NF/S-L, 60V, 0,5A, 5W, 1,5MHz	2a	USA	(BD137, BD167, BD525, BD825,++)
2N1068	Si-N	=2N1067: 1,5A, 10W	2a	USA	(BD137, BD167, BD525, BD825,++)
2N1069	Si-N	NF/S-L, 60V, 4A, 50W	23a	USA	BD245A, BDV91, 2N4914..15, 2N5068..69++
2N107	Ge-P	NF, 12V, 0,01A, 0,05W	1a	USA	AC125..126, AC151, 2SB54, 2SB56
2N1070	Si-N	NF/S-L, 60V, 4A, 50V	23a	USA	BD245A, BDV91, 2N4914..15, 2N5068..69++
2N1072	Si-N	NF/S, -/30V, 2A(ss), 12W	≈2a	Sty	(BD135, BD165, BD509, BD825,++)
2N1073	Ge-P	NF/S-L, 40V, 10A, 85W	23a	USA,Mot	AL100..101, AUY21, 2N8611..18,++
2N1073A	Ge-P	=2N1073: 80V	23a		AL100..101, AUY37, 2N8615..18,++
2N1073B	Ge-P	=2N1073: 120V	23a		AL100, AUY38, 2N2290, 2N2293
2N1074	Si-N	NF, 50V, 0,05A, 0,25W, β=14	2a	Ray,Sty	BC167, BC182, BC237, BC547,++
2N1075	Si-N	=2N1074: β=25	2a	Ray,Sty	BC167, BC182, BC237, BC547,++
2N1076	Si-N	=2N1074: β=50	2a	Ray,Sty	BC167, BC182, BC237, BC547,++
2N1077	Si-N	=2N1074: β=18	2a	Ray,Sty	BC167, BC182, BC237, BC547,++
2N1076	Ge-P	NF/S-L, 60V, 3A, 20W		USA	—
2N1079	Si-N	NF/S-L, 60V, 3A, 60W		USA	2N1722..23, (BD241A, BD535, BD935,++)
2N108	Ge-P	NF, 20V, 0,015A, 0,05W	≈2a	Csr,Etc	AC125..126, AC151, 2SB54, 2SB56
2N1060	Si-N	NF/S-L, 60V, 3A, 60W		USA	2N1722..23, (BD241A, BD535, BD935,++)
2N1081	Si-N	NF/S, 40V, 0,75A, 0,6W	2a	Tra	BC140..141, BC300..302, 2N3053,++
2N1082	Si-N	Uni, 25V, 0,05A, 0,2W, >17MHz	2a	Tra	BC168, BC163, BC238, BC548,++
2N1084	Si-P	NF, 60V, 2A, 5W(Tc=100°)	2a	USA	BC481, BCX60, 2N4235..36
2N1085	Si-N	NF, 60V, 2A, 5W(Tc=100°)	2a	USA	BC441, BCX40, 2N4238..39
2N1086(A)	Ge-N	NF/HF, 20V, 0,2A, 0,065W, 8MHz	2a	USA	—
2N1087	Ge-N	NF/HF, 20V, 0,2A, 0,065W, 8MHz	2a	USA	—
2N109	Ge-P	NF, 35V, 0,15A, 0,165W	1a	USA	AC125..126, AC151, 2SB54, 2SB56
2N109/5	Ge-P	NF, 25V, 0,07A, 0,15W	2a	Syl	AC125..126, AC151, 2SB54, 2SB56
2N1090	Ge-N	NF/S, 25V, 0,4A, 0,12W, 7MHz	2a	USA	ASY73..75
2N1091	Ge-N	NF/S, 25V, 0,4A, 0,12W, 13MHz	2a	USA	ASY73..75
2N1092	Si-N	NF/S, 60V, 0,5A, 1,5MHz	2a	USA	BC140..141, BC300..302, 2N1813,++
2N1093	Ge-P	NF/S, 30V, 0,3A, 0,15W	2a	USA	AC125..126, AC151..152, 2SB324
2N1094	Ge-P	UHF, 30V, 0,04A, 0,15W, 645MHz	2a	Whs	AF138, AF239S
2N1095	Si-N	NF/S, 60V, 0,5W, 3MHz	2a	USA	BC140..141, BC300..302, 2N3053,++
2N1096	Si-N	NF/S, 90V, 0,5W, 3MHz	2a	USA	BC141, BC300..301, 2N1889..90,++
2N1097	Ge-P	NF, -/16V, 0,1A, 0,14W, B>34	2a	USA	AC125..126, AC151, 2SB54, 2SB56
2N1098	Ge-P	=2N11097: B>25	2a	USA	AC125..126, AC151, 2SB54, 2SB56
2N1099	Ge-P	NF/S-L, 60V, 15A, 170W	38a	USA, Mot	2N1962, 2N2075, 2N2079, 2N2492..93,++
2N110	Ge-P	S, 50V, 0,04A, 0,2W	≈1a	Wes	—
2N1100	Ge-P	=2N1099: 100V	38a	USA, Mot	2N2493
2N1101	Ge-N	NF, 20V, 0,1A, 0,18W	2a	USA	AC127, ASY28..29, ASY73..75
2N1102	Ge-N	=2N1101: 40V	≈1a	USA	—
2N1103	Si-N	NF/S, 45V, 0,02A, 0,125W, >10MHz	2a	USA	BC167, BC182, BC237, BC547,++
2N1104	Si-N	NF/S, 45V, 0,02A, 0,125W, >20MHz	2a	USA	BC167, BC182, BC237, BC547,++
2N1105	Si-N	NF, 60V, 0,5A, 0,8W	2a	USA	BC140..141, BC300..302, 2N3053,++
2N1106	Si-N	=2N1105: 100V	2a	USA	BC141, BC300, 2N1889..90, 2N1990,++
2N1107	Ge-P	HF, 16V, 50mA, 0,03W, 40MHz	2a	USA	AF124..126, AF200
2N1108	Ge-P	HF, 16V, 50mA, 0,03W, 35MHz	2a	USA	AF124..126, AF200
2N1109	Ge-P	HF, 16V, 50mA, 0,03W, 35MHz	2a	USA	AF124..126, AF200
2N111(A)	Ge-P	HF, 30V, 0,2A, 0,13W, 3MHz	2a	Csr,Etc	ASY26, 2N3323..25
2N1110	Ge-P	HF, 16V, 5mA, 0,03W, 35MHz	2a	USA	AF124..126, AF200
2N1111(A,B)	Ge-P	HF, 20V, 5mA, 0,03W, 35MHz	2a	USA	AF124..126, AF200
2N1114	Ge-N	NF/S, 25V, 0,2A, 0,15W, >7MHz	2a(B=case)	USA	AC127, ASY28..29, ASY73..75
2N1115(A)	Ge-P	NF/S, 20V, 0,125A, 0,15W, >5MHz	1a	USA	AC125..126, AC151, ASY26..27
2N1116	Si-N	NF/S, 60V, 0,8A, 0,6W(Ta=100°), >6MHz	2a	USA	BC140..141, BC300..302, 2N3053,++
2N1117	Si-N	NF/S, 60V, 0,8+C10325A, 0,6W(Ta=100°), >4MHz	5e	USA	BC140..141, BC300..302, 2N3053,++
2N1118(A)	Si-P	Uni, 25V, 0,05A, 0,15W	5a	USA	BC213, BC256, BC306, BC556,++
2N1119	Si-P	Uni, 10V, 0,05A, 0,15W	2a	USA	BC213, BC258, BC306, BC556,++
2N112(A)	Ge-P	HF, 30V, 0,2A, 0,13W, 5MHz	2a	Csr,Etc	ASY26, 2N3323..25
2N1120	Ge-P	NF/S-L, 80V, 15A, 90W	23a	USA, Mot	2N1551..52, 2N1555..56, 2N1559..60
2N1121	Ge-N	HF, 25V, 0,2A, 0,065W, 8MHz	2a	USA	—
2N1122	Ge-P	HF/S/Chopper, 12V, 0,05A, 0,025W	37d	Spr,Ssi	—
2N1122A	Ge-P	=2N1122: 15V	37d		—
2N1123	Ge-P	NF/S, 45V, 0,5A, 0,75W	37d*	USA	(2N1189..90)

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2N1124	Ge-P	NF/S, 40V, 0,25A, 0,3W	2a	USA	2N1189..90, 2SB405ST
2N1125	Ge-P	NF/S, 40V, 0,25A, 0,3W	2a	USA	2N1189..90, 2SB405ST
2N1126	Ge-P	=2N1124: 1W	2a*	USA	(2N1189..90, 2SB405ST)
2N1127	Ge-P	=2N1125: 1W	2a*	USA	(2N1189..90, 2SB405ST)
2N1128	Ge-P	NF, 25V, 0,25A, 0,15W	2a	USA	AC128, AC152..153, AC188, 2SB324
2N1129	Ge-P	NF, 25V, 0,25A, 0,15W	2a	USA	AC128, AC152..153, AC188, 2SB324
2N113	Ge-P	HF, 30V, 0,2A, 0,13W, 10MHz	≈1a	Csr,Etc	ASY28, 2N3323..25
2N1130	Ge-P	NF, 30V, 0,25A, 0,15W	2a	USA	AC126, AC152..153, AC188, 2SB324
2N1131	Si-P	NF/S, 90V, 0,6A, 0,6W, >50MHz	2a	USA,EUR	BC161, BC303..304, 2N2904..05(A),++
2N1131A,AS	Si-P	=2N1131: 60V	2a		BC161, BC303..304, 2N2904..05(A),++
2N1132	Si-P	NF/S, 90V, 0,6A, 0,6W, >60MHz	2a	USA,EUR	BC161, BC303..304, 2N2904..05(A),++
2N1132A	Si-P	=2N1132: 60V	2a		BC161, BC303..304, 2N2904..05(A),++
2N1132B	Si-P	=2N1132: 75V	2a		BC303, BSW40, 2N4031, 2N4033,++
2N1135(A)	Si-P	Uni, 12/12/12V, 0,05A, 0,1A, >5,8MHz	5e	Phc	(BC213, BC258, BC308, BC558,++
2N1136	Ge-P	NF/S-L, 60V, 6A, 60W, B>50	23a	USA	AL102..103, AUY28, 2N3615..18,++
2N1136A	Ge-P	=2N1136: 90V	23a		AL102..103, AUY28, 2N3616, 2N3618
2N1136B	Ge-P	=2N1136: 100V	23a		AL102..103, AUY37, 2N3616, 2N3618
2N1137	Ge-P	NF/S-L, 60V, 6A, 60W, B>75	23a	USA	AL102..103, AUY28, 2N3615..18,++
2N1137A	Ge-P	=2N1137: 90V	23a		AL102..103, AUY28, 2N3616, 2N3616
2N1137B	Ge-P	=2N1137: 100V	23a		AL102..103, AUY37, 2N3618, 2N3616
2N1138	Ge-P	NF/S-L, 60V, 6A, 60W, B>100	23a	USA	AL102..103, AUY28, 2N3615..18,++
2N1138A	Ge-P	=2N1138: 90V	23a		AL102..103, AUY28, 2N3618, 2N3618
2N1138B	Ge-P	=2N1138: 100V	23a		AL102..103, AUY37, 2N3616, 2N3618
2N1139	Si-N	S, 15V, 0,1A, 0,5W(Ta=100°), >100MHz	2a	USA	BSV69, 2N3724, 2SC1072, 2SC1365,++
2N114	Ge-P	HF, 30V, 0,2A, 0,13W, 20MHz	≈1a	Csr,Etc	ASY2S, 2N3323..25
2N1140	Si-N	S, 40V, 1W(Ta=100°), >35MHz	2a	USA	BSV69, 2N3724, 2SC1072, 2SC1365,++
2N1141(A)	Ge-P	VHF/UHF, 35V, 0,1A, 0,3W, >1200MHz	2a	Mot,Ssm,Tix	(AFY18)
2N1142(A)	Ge-P	VHF/UHF, 35V, 0,1A, 0,3W, >1000MHz	2a	Mot,Sam,Tix	(AFY16)
2N1143(A)	Ge-P	VHF/UHF, 35V, 0,1A, 0,3W, >800MHz	2a	Mot,Sam,Tix	(AFY16)
2N1144	Ge-P	NF, 16V, 0,1A, 0,14W, β=55	1a	USA	AC125..126, AC151, 2SB54, 2SB56
2N1145	Ge-P	=2N1144: β=45	1a	USA	AC125..126, AC151, 2SB54, 2SB56
2N1146	Ge-P	NF/S-L, 40V, 15A, 90W	23a	USA	2N1549..60
2N1146A	Ge-P	=2N1146: 60V	23a		2N1550..52, 2N1554..56, 2N1558..60
2N1146B	Ge-P	=2N1146: 60V	23a		2N1551..52, 2N1555..56, 2N1559..60
2N1146C	Ge-P	=2N1146: 100V	23a		2N1552, 2N1556, 2N1560
2N1147	Ge-P	NF/S-L, 40V, 15A, 90W	23a	USA	2N1549..60
2N1147A	Ge-P	=2N1147: 60V	23a		2N1550..52, 2N1554..56, 2N1558..60
2N1147B	Ge-P	=2N1147: 60V	23a		2N1551..52, 2N1555..56, 2N1559..60
2N1147C	Ge-P	=2N1147: 100V	23a		2N1552, 2N1556, 2N1560
2N1149	Si-N	Uni, 45V, 0,6A, 0,15W, 12MHz	5e	USA	BC167, BC182, BC237, BC547,++
2N115	Ge-P	NF/S-L, 32V, 3A, 50W		Amp	—
2N1150	Si-N	Uni, 45V, 0,6A, 0,15W, 13MHz	5e	USA	BC167, BC182, BC237, BC547,++
2N1151	Si-N	Uni, 45V, 0,6A, 0,15W, 14MHz	5e	USA	BC167, BC182, BC237, BC547,++
2N1152	Si-N	Uni, 45V, 0,6A, 0,15W, 15MHz	5e	USA	BC167, BC182, BC237, BC547,++
2N1153	Si-N	Uni, 45V, 0,6A, 0,15W, 16MHz	5e	USA	BC167, BC182, BC237, BC547,++
2N1154	Si-N	Uni, 50V, 0,06A, 0,75W, 1MHz	5e	USA	BC140..141, BC300..302, 2N3053,++
2N1155	Si-N	=1154: 80V 0,05A		USA	BC140..141, BC300..301, 2N1889..90,++
2N1156	Si-N	=2N1154: 120V, 0,04A	5a	USA	BC300, 2N1893(A), 2N2102, 2N2405,++
2N1157	Ge-P	S-L, 60V, 40A, 187W	≈49m	USA	—
2N1157A	Ge-P	=2N1157: 80V	≈49m	USA	—
2N1158(A)	Ge-P	HF, 20V, 0,1A, 0,06..0,075W	2a	Csr,Etc	—
2N1159	Ge-P	NF/S-L, 60V, 5A, 90W	23a	USA	AL102..103, AUY22, 2N3615..18,++
2N116	Ge-P			Cbs	—
2N1160	Ge-P	=2N1159: 7A	23a	USA	AL102..103, AUY22, 2N3+F10445615..18,++
2N1162(A)	Ge-P	NF/S-L, 50V, 25A, 106W	23a	USA, Mot	2N1651..53, 2N2285..87
2N1163(A)	Ge-P	NF/S-L, 50V, 25A, 106W	23a	USA, Mot	2N1651..53, 2N2285..87
2N1164(A)	Ge-P	NF/S-L, 60V, 25A, 106W	23a	USA, Mot	2N1652..53, 2N2288..87
2N1165(A)	Ge-P	NF/S-L, 80V, 25A, 106W	23a	USA, Mot	2N1652..53, 2N2286..87
2N1166(A)	Ge-P	NF/S-L, 100V, 25A, 106W	23a	USA, Mot	2N1653, 2N2287
2N1167(A)	Ge-P	NF/S-L, 100V, 25A, 106W	23a	USA, Mot	2N1653, 2N2287
2N1168	Ge-P	NF/S-L, 50V, 5A, 45W	23a	USA	AL102..103, AUY22, 2N1545..48,++
2N1169	Ge-N	NF/S/Chopper, 40V, 0,4A, 0,12W	2a	Csr,Sty	—
2N117	Si-N	NF/S, 45V, 600mA, 0,15W, β>9	5e	USA	BC167, BC182, BC237, BC547,++
2N1170	Ge-N	NF/S/Chopper, 40V, 0,4A, 0,12W	2a	Csr,Sty	—
2N1171	Ge-P	NF/S, 30V, 0,4A, 0,17W, >10MHz	2a	Mot	AC128, AC152..153, ASY26, ASY76..77
2N1172	Ge-P	NF/S, 40V, 1,5A(ss), 5W	43m	USA	(AD162)

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2N1173	Ge-N	NF/S, 35V, 0,2A, 0,25W	2a	Wes	—
2N1174	Ge-P	NF/S, 35V, 0,2A, 0,25W	2a	Wes	—
2N1175(A)	Ge-P	NF/S, 35V, 0,5A, 0,225W, 4,2MHz	2a(B=case)	USA, Mot	AC128, AC152..153, ASY78..77
2N1176	Ge-P	NF, 10V, 0,3A, 0,3W	2a	USA	AC128, AC152..153, 2SB324, 2SB415
2N1176A	Ge-P	=2N1176: 40V	2a		ASY48, ASY76..77, 2SB405ST
2N1176B	Ge-P	=2N1176: 60V	2a		ASY46, ASY77
2N1177	Ge-P	HF, 40V, 10mA, 0,08W, 140MHz	1g	Cen, Rca, Sgs	AF106, AF109R, AF306
2N1178	Ge-P	HF, 40V, 10mA, 0,06W, 140MHz	1g	Cen, Rca, Sgs	AF106, AF109R, AF306
2N1179	Ge-P	HF, 40V, 10mA, 0,08W, 140MHz	1g	Cen, Rca, Sgs	AF106, AF109R, AF306
2N118(A)	Si-N	=2N117: β>19	5e	USA	BC167, BC182, BC237, BC547, ++
2N1180	Ge-P	HF, 40V, 10mA, 0,08W, 100MHz	1g	Cen, Rca, Sgs	AF106, AF109R, AF306
2N1162	Ge-P	NF/S-L, -/80V, 5A, 106W	23a	Cen, Gpd	2N1541..43, 2N1546..48, 2N3615..16, ++
2N1163	Ge-P	NF/S-L, 45V, 3A, 7,5W, B>20	2a	Gpd, Stc	AUY16
2N1163A	Ge-P	=2N1183: 80V	2a		AUY18
2N1183B	Ge-P	=2N1183: 80V	2a		—
2N1184	Ge-P	NF/S-L, 45V, 3A, 7,5W, B>40	2a	Gpd, Stc	AUY16
2N1184A	Ge-P	=2N1184: 60V	2a		AUY16
2N1164B	Ge-P	=2N1164: 80V	2a		—
2N1165	Ge-P	NF/S, 45V, 0,5A, 0,2W, 3MHz, β>190	2a	USA, Mot	ASY76..77
2N1166	Ge-P	NF/S, 60V, 0,5A, 0,2W, 1,5MHz, β>30	2a	USA, Mot	ASY77
2N1187	Ge-P	NF/S, 80V, 0,5A, 0,2W, 2MHz, β>50	2a	USA, Mot	ASY77
2N1188	Ge-P	NF/S, 80V, 0,5A, 0,2W, 2,5MHz, β>100	2a	USA, Mot	ASY77
2N1189	Ge-P	NF/S, 45V, 0,5A, 0,2W, 3,5MHz, β>75	2a	USA, Mot	ASY76..77, 2SB405ST
2N119	Si-N	=2N117: β>38	5e	USA	BC167, BC162, BC237, BC547, ++
2N1190	Ge-P	NF/S, 45V, 0,5A, 0,2W, 4,5MHz, β>125	2a	USA, Mot	ASY76..77, 2SB405ST
2N1191	Ge-P	NF/S, 40V, 0,2A, 0,2W, 1,5MHz, β>30	2a	USA, Mot	ASY48, ASY76..77, 2SB56A
2N1192	Ge-P	NF/S, 40V, 0,2A, 0,2W, 2MHz, β>50	2a	USA, Mot	ASY48, ASY76..77, 2SB56A
2N1193	Ge-P	NF/S, 40V, 0,2A, 0,2W, 2,5MHz, β>100	2a	USA, Mot	ASY48, ASY76..77, 2SB56A
2N1194	Ge-P	NF/S, 40V, 0,2A, 0,2W, 3MHz, β>190	2a	USA, Mot	ASY48, ASY76..77, 2SB56A
2N1195	Ge-P	UHF, 30V, 0,04A, 0,225W, >1200MHz	2a	Mot, Spe	2N1141..43
2N1196	Si-P	Uni, 70V, 1A, 0,35	5e	USA	BC212, BC256, BC266, BC556, ++
2N1197	Si-P	Uni, 90V, 1A, 0,35	2a	USA	BC212, BC256, BC266, BC556, ++
2N1196	Ge-N	NF/S, 25V, 0,3A, 0,065W, 9MHz	2a	USA	ASY26..29, ASY73..75
2N1199(A)	Si-N	HF/S, 20V, 0,1A, 0,15W, 125MHz	2a	Etc, Phc	BSV89..92, BSX92..93, 2N2368..69(A), ++
2N120	Si-N	=2N117: β>76	5e	USA	BC167, BC182, BC237, BC547, ++
2N1200	Si-N	HF, 20V, 0,1A, 0,1W, 4,3MHz	2a	Phc	BC166, BC163, BC236, BC548, ++
2N1201	Si-N	=2N1200: 12MHz	2a	Phc	BC168, BC183, BC238, BC546, ++
2N1202	Ge-P	S-L, 80V, 3,5A, 34W	≈37b	USA	—
2N1203	Ge-P	=2N1202: 120V	≈37b	USA	—
2N1204(A)	Ge-P	S, 20V, 0,5A, 0,3W, 200MHz	2a	USA, Mot	2N1495, 2N2099..2100
2N1205	Si-N	Uni, 20V, 0,15W, >17MHz	2a	USA	BC166, BC183, BC238, BC548, ++
2N1206	Si-N	NF/S, 60V, 0,15A, 3W(Tc=100°), >10MHz	2a	USA	BC140..141, BC300..302, 2N3053, ++
2N1207	Si-N	=2N1206: 125V	2a	USA	BC300, 2N1893(A), 2SC959, 2SC2106, ++
2N1206(/I)	Si-N	S-L, 80V, 5A, 45..80W	49m	USA	2N3467..92
2N1209(/I)	Si-N	S-L, 45V, 5A, 45..80W	49m	USA	2N3487..92
2N1210(/I)	Si-N	S-L, 60V, 5A, 45..80W		USA	2N1722..23
2N1211(/I)	Si-N	S-L, 80V, 5A, 45..80W		USA	2N1722..23
2N1212(/I)	Si-N	S-L, 80V, 5A, 45..80W	49m	USA	2N8437..92
2N1217	Ge-N	NF/S, 20V, 0,025A, 0,075W, 9MHz	2a	Csr, Etc	—
2N1218	Ge-N	NF/S-L, 45V, 3A, 20W	23a	USA	—
2N1219	Si-P	Uni, 30V, 0,1A, 0,25W, >5MHz	2a	USA	(BC213, BC258, BC306, BC558, ++)
2N122	Si-N	NF/S-L, 120V, 0,14A, 9W		Csr, Ssi	(BD424, MJE340, 2SC2376, 2SC2461, ++)
2N1220	Si-P	Uni, 30V, 0,1A, 0,25W, >2MHz	2a	USA	(BC213, BC258, BC306, BC558, ++)
2N1221	Si-P	Uni, 30V, 0,1A, 0,25W	2a	USA	(BC213, BC258, BC308, BC558, ++)
2N1222	Si-P	Uni, 30V, 0,1A, 0,25W, >2MHz	2a	USA	(BC213, BC258, BC306, BC556, ++)
2N1223	Si-P	Uni, 40V, 0,1A, 0,25W, 2MHz	2a	USA	(BC212, BC257, BC307, BC557, ++)
2N1224	Ge-P	HF, 40V, 10mA, 0,12W, 30MHz	5g	USA	AF124..126, AF200
2N1225	Ge-P	HF, 40V, 10mA, 0,12W, 100MHz	5g	USA	AF124..125, AF200
2N1226	Ge-P	HF, 80V, 10mA, 0,12W, 30MHz	5g	USA	AF118
2N1227	Ge-P	NF/S-L, 35V, 3A, 50W	23a	USA	AD149, AUY19..20, 2N2144..46, ++
2N1228	Si-P	Uni, 15V, 0,1A, 0,4W, 1,2MHz, β>14	2a	USA	(BC213, BC256, BC308, BC558, ++)
2N1229	Si-P	=2N1226: β>26	2a	USA	(BC213, BC256, BC308, BC558, ++)
2N123	Ge-P	S, 20V, 0,125A, 0,15W	1a	USA	ASY26..27, ASY48, ASY76..77
2N1230	Si-P	Uni, 35V, 0,1A, 0,4W, 1,2MHz, β>14	2a	USA	(BC213, BC258, BC306, BC558, ++)
2N1231	Si-P	=2N1230: β>26	2a	USA	(BC213, BC258, BC306, BC558, ++)
2N1232	Si-P	Uni, 60V, 0,1A, 0,4W, 1MHz, β>14	2a	USA	(BC212, BC256, BC266, BC558, ++)

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2N1232A	Si-P	=2N1232: 90V	2a		(2SC1890,2SC2240,2SC2459,2SC3245,++)
2N1233	Si-P	=2N1232: β>28	2a	USA	(BC212,BC258,BC266,BC556,++)
2N1234	Si-P	Uni,110V,0,1A,0,4W,0,8MHz,β>4	2a	USA	(2SC1890A,2SC2240,2SC2459,2SC3245,++)
2N1235	Si-N	S-L,120V,2A,85W	49m	USA	2N3489,2N3492,2N5284..85
2N1238..1244	Si-P	=2N1228..1234: 1W	Koax	Sem,Sty	→2N1228..1234
2N123A(/5)	Ge-P	=2N123:	2a	Syl	ASY28..27,ASY48,ASY76..77
2N124	Ge-N	S,20V,300mA,0,05W,3MHz	2a	Csr,Etc	ASY28..27,ASY48,ASY76..77
2N1245	Ge-P	NF-L,30V,4A,20W	23a	Cen	AD149,AUY28,2N1529..48,2SB449,++
2N1246	Ge-P	NF-L,30V,4A,20W	23a	Cen	AD149,AUY28,2N1529..46,2SB449,++
2N1247	Si-N	Uni,6V,5mA,0,03W,5MHz,B>15	2a	USA	(BC168,BC183,BC238,BC548,++)
2N1246	Si-N	Uni,6V,5mA,0,03W,5MHz,B>15	2a	USA	(BC188,BC183,BC238,BC548,++)
2N1249	Si-N	Uni,6V,5mA,0,03W,5MHz,B>20	2a	USA	(BC188,BC183,BC238,BC546,++)
2N125	Ge-N	S,10V,6mA,0,05W,5MHz	2a	Csr,Etc	ASY28..27,ASY48,ASY76..77
2N1250(/1)	Si-N	NF/S-L,60V,5A,75..85W		USA	2N1722..23,(BD245A,BD545A,BDV91++)
2N1251	Ge-N	NF/S,20V,0,1A,0,15W	2a	USA	AC127,ASY28..29,ASY73..75
2N1252	Si-N	NF/S,30V,1A,0,6W,>40MHz,B>15	2a	USA,Tix	BC140..141,BC300..302,2N2218..19,++
2N1252A	Si-N	=2N1252: 60V	2a		BC140..141,BC300..302,2N2218..19,++
2N1253	Si-N	NF/S,30V,1A,0,6W,>50MHz,B>30	2a	USA,Tix	BC140..141,BC300..302,2N2218..19,++
2N1253A	Si-N	=2N1253: 60V	2a		BC140..141,BC300+F10700..302,2N2216..19,++
2N1254	Si-P	Uni,30V,0,1A,0,275W,<25/40ns	2a	USA	BC213,BC308,BC558,BSX38,++
2N1255	Si-P	Uni,30V,0,1A,0,275W,<25/60ns	2a	USA	BC213,BC308,BC558,BSX38,++
2N1256	Si-P	Uni,40V,0,1A,0,275W,<25/40ns	2a	USA	BC212,BC307,BC557,BSX38,++
2N1257	Si-P	Uni,40V,0,1A,0,275W,<25/60ns	2a	USA	BC212,BC307,BC557,BSX38,++
2N1258	Si-P	Uni,40V,0,1A,0,275W,<25/60ns	2a	USA	BC212,BC307,BC557,BSX36,++
2N1259	Si-P	Uni,50V,0,1A,0,275W,<25/60ns	2a	USA	BC212,BC307,BC557,BSX38,++
2N128	Ge-N	S,10V,8mA,0,05W,5MHz	2a	Csr,Etc	ASY26..27,ASY46,ASY76..77
2N1260	Si-N	S-L120V,2A,65W		USA	2N1722..23,(2SD731,2SD896)
2N1261(A)	Ge-P	S-L,80V,3,5A,34W,B>20	≈37b	USA	—
2N1262(A)	Ge-P	=2N1281(A): B>30	≈37b	USA	—
2N1263(A)	Ge-P	=2N1261(A): B>45	≈37b	USA	—
2N1264	Ge-P	HF,20V,10mA,0,05W,3MHz	1g	Syl	AF124..127,AF200
2N1264/13	Ge-P	=2N1264:	≈37b		—
2N1265	Ge-P	NF,20V,0,1A,0,1W	2a	USA	AC125..126,AC151,2SB54,2SB56
2N1265/5	Ge-P	=2N1265: 10V,0,05W	2a		AC125..126,AC151,2SB54,2SB56
2N1266	Ge-P	NF,-/10V,0,06W	2a	USA	AC125..126,AC151,2SB54,2SB56
2N1267	Si-N	Uni,20V,0,1A,0,15W,β>6	2a	Etc	BC166,BC183,BC238,BC548,++
2N1266	Si-N	=2N1267: β>11	2a	Etc	BC168,BC183,BC238,BC546,++
2N1269	Si-N	=2N1267 β>28	2a	Etc	BC168,BC183,BC236,BC546,++
2N127	Ge-N	S,20V,300mA,0,05W,5MHz	2a	Tix	ASY26..27,ASY48,ASY76..77
2N1270	Si-N	=2N1287:	2a	Etc	BC168,BC183,BC238,BC546,++
2N1271	Si-N	=2N1267: β>11	2a	Etc	BC168,BC183,BC238,BC548,++
2N1272	Si-N	=2N1287: β>28	2a	Etc	BC168,BC163,BC238,BC546,++
2N1273	Ge-P	NF/S,15V,0,2A,0,25W	2a	USA,Tix	AC125..126,AC151,2SB54,2SB56
2N1274	Ge-P	=2N1273: 25V	2a	USA,Tix	AC125..126,AC151,2SB54,2SB56
2N1275	Si-P	NIX,100V,0,05A,0,25W	2a	USA	BF398,BSS66,BSV68,2SB715..716,++
2N1276	Si-N	Uni,40V,0,025A,0,15W,β>9	2a	USA,Tix	BC167,BC182,BC237,BC547,++
2N1277	Si-N	=2N1276: β>18	2a	USA,Tix	BC167,BC182,BC237,BC547,++
2N1278	Si-N	=2N1276: β>37	2a	USA,Tix	BC167,BC182,BC237,BC547,++
2N1279	Si-N	=2N1276 β>76	2a	USA,Tix	BC167,BC162,BC237,BC547,++
2N126	Ge-P	HF,10V,5mA,0,025W,>26MHz	37d	Spr,Ssi	AF124..127,AF200
2N1280	Ge-P	NF/S,16V,0,4A,0,2W,>5MHz,B>40	2a	USA	ASY76..77
2N1261	Ge-P	NF/S,16V,0,4A,0,2W,>7MHz,B>60	2a	USA	ASY76..77
2N1282	Ge-P	NF/S,16V,0,4A,0,2W,>10MHz,B>70	2a	USA	ASY76..77
2N1264	Ge-P	S,20V,0,4A,0,15W,8MHz	2a	USA	ASY76..77
2N1265	Ge-P	HF,40V,10mA,0,12W,100MHz	5g	Sty	AF124..125,AF200
2N1287(A)	Ge-P	NF/S,25V,0,3A,0,3W,1MHz	49a	Cen,Gpd	—
2N1268	Ge-N	S,15V,0,05A,0,075W,60MHz	2a	Gen,Sty	—
2N1269	Ge-N	=2N1268: 20V	2a	Gen	—
2N129	Ge-P	HF,10V,5mA,0,03W,30MHz	37d	Spr	AF124..127,AF200
2N1291	Ge-P	NF/S-L,35V,3A,20W	23a	USA	AD149,AUY19..20,2N2143..46,++
2N1292	Ge-N	NF/S-L,35V,3A,25W	23a	USA	2N1218
2N1293	Ge-P	=2N1291: 60V	23a	USA	AL102..103,AUY19..20,2N2144..46,++
2N1294	Ge-N	=2N1292: 60V	23a	USA	—
2N1295	Ge-P	=2N1291: 60V	23a	USA	AL102..103,AUY20,2N2141,2N2146,++
2N1296	Ge-N	=2N1292: 80V	23a	USA	—
2N1297	Ge-P	=2N1291: 100V	23a	USA	AL102..103,AUY34,2N2141,2N2146,++

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2N1298	Ge-N	=2N1292: 100V	23a	USA	—
2N1299	Ge-N	NF/S, 40V, 0,2A, 0,15W, 5MHz	2a(B=case)	USA	—
2N130	Ge-P	NF, 25V, 0,01A, 0,085W	2a	USA	AC125..126, AC151, ASY26..27
2N1300	Ge-P	HF/S, 13V, 0,1A, 0,15W, 40MHz	2a	USA	—
2N1301	Ge-P	=2N1300: 60MHz	2a	USA	—
2N1302	Ge-N	NF/S, 25V, 0,3A, 0,15W, 5MHz, B>20	2a(B=case)	USA, Phi, Tho	ASY26..29, ASY73..75
2N1303	Ge-P	NF/S, 30V, 0,3A, 0,15W, 5MHz, B>20	2a(B=case)	USA, Phi, Tho	ASY26, ASY76..77
2N1304	Ge-N	NF/S, 25V, 0,3A, 0,15W, 10MHz, B>40	2a(B=case)	USA, Phi, Tho	ASY28..29, ASY73..75
2N1305	Ge-P	NF/S, 30V, 0,3A, 0,15W, 10MHz, B>40	2a(B=case)	USA, Phi, Tho	ASY26, ASY76..77
2N1306	Ge-N	NF/S, 25V, 0,3A, 0,15W, 15MHz, B>60	2a(B=case)	USA, Phi, Tho	ASY28..29, ASY73..75
2N1307	Ge-P	NF/S, 30V, 0,3A, 0,15W, 15MHz, B>60	2a(B=case)	USA, Phi, Tho	ASY26, ASY76..77
2N1308	Ge-N	NF/S, 25V, 0,3A, 0,15W, 25MHz, B>80	2a(B=case)	USA, Phi, Tho	ASY28..29, ASY73..75
2N1309(A)	Ge-P	NF/S, 30V, 0,3A, 0,15W, 20MHz, B>80	2a(B=case)	USA, Phi, Tho	ASY26, ASY76..77
2N130A	Ge-P	NF, 45V, 0,1A, 0,1W	≈40e		ASY48, ASY76..77
2N131	Ge-P	NF, 25V, 0,01A, 0,085W	2a	USA	AC125..126, AC151, ASY26..27
2N1310	Ge-N	Nix, 90V, 0,12W	2a	USA	—
2N1311	Ge-N	Nix, 75V, 0,12W	2a	USA	—
2N1312	Ge-N	Nix, 50V, 0,12W	2a	USA	—
2N1313	Ge-P	NF/S, 30V, 0,4A, 0,18W, 12MHz	2a	USA	ASY76..77
2N1314	Ge-P	NF/S-L, 40V, 3,5A, 12W(Tc=70°)	23a	USA	AD149, AUY19..20, 2N2143..46,++
2N1315	Ge-P	NF/S-L, 32V, 3,5A, 12W(Tc=70°)	23a	USA	AD149, AUY19..20, 2N2137..46,++
2N1316	Ge-P	NF/S, 30V, 0,4A, 0,2W, >10MHz	2a	USA	ASY76..77
2N1317	Ge-P	NF/S, 20V, 0,4A, 0,2W, >10MHz	2a	USA	ASY76..77
2N1318	Ge-P	NF/S, 10V, 0,4A, 0,2W, >10MHz	2a	USA	ASY76..77
2N1319	Ge-P	NF/S, 20V, 0,4A, 0,2W, 6MHz	2a	USA	ASY76..77
2N131A	Ge-P	NF, 45V, 0,1A, 0,1W	≈40e		ASY48, ASY76..77
2N132	Ge-P	NF, 25V, 0,01A, 0,085W	2a	USA	AC125..126, AC151, ASY26..27
2N1320	Ge-P	NF/S-L, 35V, 3A, 20W	≈37b	Gpd, Stc	—
2N1321	Ge-N	NF/S-L, 35V, 3A, 25W	≈37b	Gpd, Stc	—
2N1322	Ge-P	=2N1320: 60V	≈37b	Gpd, Stc	—
2N1323	Ge-N	=2N1321: 60V	≈37b	Gpd, Stc	—
2N1324	Ge-P	=2N1320: 60V	≈37b	Gpd, Stc	—
2N1325	Ge-N	=2N1321: 60V	≈37b	Gpd, Stc	—
2N1326	Ge-P	=2N1320: 100V	≈37b	Gpd, Stc	—
2N1327	Ge-N	=2N1321: 100V	≈37b	Gpd, Stc	—
2N1326	Ge-P	=2N1320:	≈37b	Gpd, Stc	—
2N1329	Ge-N	=2N1321:	≈37b	Gdp, Stc	—
2N132A	Ge-P	NF, 35V, 0,1A, 0,1W	≈40e		ASY48, ASY76..77
2N133	Ge-P	NF, 25V, 0,01A, 0,085W	2a	USA	AC125..126, AC151, ASY26..27
2N1330	Ge-N	=2N1321: 60V	≈37b	Gpd, Stc	—
2N1331	Ge-P	=2N1320: 60V	≈37b	Gpd, Stc	—
2N1332	Ge-N	=2N1321: 60V	≈37b	Gpd, Stc	—
2N1333	Ge-P	=2N1320: 100V	≈37b	Gpd, Stc	—
2N1334	Ge-N	=2N1321: 100V	≈37b	Gpd, Stc	—
2N1335	Si-N	HF-Tr, 120V, 0,3A, PQ>0,25W(70MHz)	2a	USA	—
2N1336	Si-N	HF-Tr, 120V, 0,3A, PQ>0,5W(70MHz)	2a	USA	—
2N1337	Si-N	HF-Tr, 120V, 0,3A, PQ>0,7W(70MHz)	2a	USA	—
2N1336	Si-N	HF-Tr, 80V, 0,3A, PQ>0,5W(70MHz)	2a	USA	—
2N1339	Si-N	HF-Tr, 120V, 0,3A, PQ>0,25W(70MHz)	2a	USA	—
2N133A	Ge-P	NF, 35V, 0,1A, 0,1W	≈40e		ASY48, ASY76..77
2N1340	Si-N	HF-Tr, 150V, 0,3A, PQ>0,5W(70MHz)	2a	USA	—
2N1341	Si-N	HF-Tr, 120V, 0,3A, PQ>0,75W(70MHz)	2a	USA	—
2N1342	Si-N	HF-Tr, 150V, 0,3A, PQ>1W(70MHz)	2a	USA	—
2N1343	Ge-P	NF/S, 20V, 0,4A, 0,15W, 6MHz	2a	USA	ASY76..77
2N1344	Ge-P	NF/S, 15V, 0,4A, 0,15W, >7MHz	2a	USA	ASY76..77
2N1345	Ge-P	NF/S, 10V, 0,4A, 0,15W, >10MHz	2a	USA	ASY76..77
2N1346	Ge-P	NF/S, 12V, 0,4A, 0,15W, >10MHz	2a	USA	ASY76..77
2N1347	Ge-P	NF/S, 20V, 0,2A, 0,15W, >5MHz	2a	USA	ASY26..27, ASY76..77
2N1348	Ge-P	NF/S, 40V, 0,4A, 0,2W, 5MHz	2a	USA	ASY76..77
2N1349	Ge-P	NF/S, 40V, 0,4A, 0,2W, 10MHz	2a	USA	ASY76..77
2N135	Ge-P	HF, 20V, 0,05A, 0,1W, 4,5MHz	1a	Csr, Etc	AF124..127, AF200, 2N3323..25
2N1350	Ge-P	NF/S, 50V, 0,4A, 0,2W, 8MHz	2a	USA	ASY76..77
2N1351	Ge-P	NF/S, 40V, 0,4A, 0,2W, 8MHz	2a	USA	ASY76..77
2N1352	Ge-P	NF/S, 30V, 0,2A, 0,15W, >2,5MHz	2a	USA	ASY26..27, ASY76..77
2N1353	Ge-P	NF/S, 15V, 0,2A, 0,2W, 3,5MHz	2a	USA	ASY26..27, ASY76..77
2N1354	Ge-P	NF/S, 30V, 0,2A, 0,2W, 4,5MHz	2a	USA	ASY26..27, ASY76..77

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2N1355	Ge-P	NF/S,30V,0,2A,0,2W,8MHz	2a	USA	ASY26..27,ASY76..77
2N1356	Ge-P	NF/S,30V,0,2A,0,2W,>5MHz	2a	USA	ASY26..27,ASY76..77
2N1357	Ge-P	NF/S,30V,0,2A,0,2W,12MHz	2a	USA	ASY26..27,ASY76..77
2N1358(A,M)	Ge-P	NF/S-L,80V,15A,150W	38a	USA,Mot	2N1982,2N2075,2N2079,2N2492..93
2N1359	Ge-P	NF/S-L,50V,3A,106W,B>35	23a	USA,Mot	2N1540..43,2N1546..48,2N3615..16
2N138	Ge-P	HF,20V,0,05A,0,1W,6,5MHz	1a	Csr,Etc	AF124..127,AF200,2N3323..25
2N1360	Ge-P	=2N1359: B>60	23a	USA,Mot	2N1540..43,2N1546..48,2N3615..16
2N1361(A)	Ge-P	NF/S,25V,0,2A,0,15..0,2W,4MHz	2a(B=case)	Cen,Gen	ASY26..27,ASY76..77
2N1362	Ge-P	NF/S-L,100V,3A,106W,B>35	23a	USA,Mot	2N1542..43,2N1547..48,2N3616,2N3618
2N1363	Ge-P	=2N1362: B>60	23a	USA,Mot	2N1542..43,2N1547..48,2N3616,2N3618
2N1364	Ge-P	=2N1362: 120V	23a	USA,Mot	2N1543,2N1548,2N2290,2N2293
2N1365	Ge-P	=2N1362: 120V,B>60	23a	USA,Mot	2N1543,2N1548,2N2290,2N2293
2N1366	Ge-N	NF/S,16V,0,025A,0,1W,>5MHz	2a	USA	—
2N1367	Ge-N	=2N1366: >2,5MHz	2a	USA	—
2N137	Ge-P	HF,20V,0,05A,0,1W,10MHz	1a	Csr,Etc	AF124..127,AF200,2N3323..25
2N1370	Ge-P	NF/S,25V,0,2A,0,25W,B>45	2a	USA,Tix	AC125..126,AC151,2SB54,2SB56
2N1371	Ge-P	=2N1370: 45V	2a	USA,Tix	2SB56A
2N1372	Ge-P	=2N1370: B>30	2a	USA,Tix	AC125..126,AC151,2SB54,2SB56
2N1373	Ge-P	=2N1370: 45V	2a	USA,Tix	2SB56A
2N1374	Ge-P	=2N1370: B>50	2a	USA,Tix	AC125..126,AC151,2SB54,2SB56
2N1375	Ge-P	=2N1370: 45V,B>50	2a	USA,Tix	2SB56A
2N1376	Ge-P	=2N1370: B>75	2a	USA,Tix	AC125..126,AC151,2SB54,2SB56
2N1377	Ge-P	=2N1370: 45V,B>75	2a	USA,Tix	2SB56A
2N1378	Ge-P	=2N1370: 12V,B>95	2a	USA,Tix	AC125..126,AC151,2SB54,2SB56
2N1379	Ge-P	=2N1370: B>95	2a	USA,Tix	AC125..126,AC151,2SB54,2SB56
2N138	Ge-P	NF/S,20V,0,05A,0,15W	2a	Etc	AC125..126,AC151,ASY26..27
2N1380	Ge-P	=2N1370: 12V,B>30	2a	USA,Tix	AC125..126,AC151,2SB54,2SB56
2N1381	Ge-P	=2N1370: B>30	2a	USA,Tix	AC125..126,AC151,2SB54,2SB56
2N1382	Ge-P	=2N1370: B>50	2a	USA,Tix	AC125..126,AC151,2SB54,2SB56
2N1383	Ge-P	=2N1370: B>30	2a	USA,Tix	AC125..126,AC151,2SB54,2SB56
2N1384	Ge-P	NF/S,30V,0,5A,0,24W,35MHz	2a	Rca	—
2N1385	Ge-P	HF/S,25V,0,1A,0,75W,>250MHz	2a	Tix	—
2N1386	Si-N	Uni,25V,0,05A,0,3W,60MHz	2a	USA	BC238,BC548,BSV59,2N2221..22(A),++
2N1387	Si-N	Uni,30V,0,05A,0,3W,50MHz	2a	USA	BC238,BC546,BSV59,2N2221..22(A),++
2N1388	Si-N	Uni,45V,0,05A,0,3W,>50MHz	2a	USA	BC237,BC547,BSV59,2N2221..22(A),++
2N1389	Si-N	Uni,50V,0,05A,0,3W,>25MHz	2a	USA	BC237,BC547,BSV59,2N2221..22(A),++
2N138A,B	Ge-P	=2N138: 45V,0,13W	≈40e	Ray	ASY48,ASY76..77
2N139	Ge-P	HF,16V,15mA,0,035W,4,7MHz	1a	Csr,Etc	AF124..127,AF200,2N3323..25
2N1390	Si-N	Uni,20V,0,05A,0,3W,>20MHz	2a	USA	BC238,BC548,BSV59,2N2221..22(A),++
2N1391	Ge-N	NF/S,25V,0,15W,>3MHz	2a	USA	AC127,ASY28..29,ASY73..75
2N1392	Opto				—
2N1393	Opto				—
2N1394	Opto				—
2N1395	Ge-P	HF,40V,10mA,0,12W,30MHz	5g	USA	AF124..126,AF200
2N1396	Ge-P	=2N1395: 100MHz	5g	USA	AF106,AF109R,AF306
2N1397	Ge-P	=2N1395: 120MHz	5g	USA	AF106,AF109R,AF306
2N1398	Ge-P	HF,-/20V,10mA,0,035W,>140MHz	5g	Tix	AF106,AF109R,AF306
2N1399	Ge-P	HF,-/20V,10mA,0,035W,>140MHz	5g	Tix	AF106,AF109R,AF306
2N1400	Ge-P	HF,16V,15mA,0,035W,7MHz	1a	Etc	AF124..127,AF200,2N3323..25
2N1400	Ge-P	HF,-/20V,10mA,0,035W,>100MHz	5g	Tix	AF106,AF109R,AF306
2N1401(A)	Ge-P	HF,-/20V,10mA,0,035W,>120MHz	5g	Tix	AF106,AF109R,AF306
2N1402	Ge-P	HF,-/20V,10mA,0,035W,>100MHz	5g	Tix	AF106,AF109R,AF306
2N1403	Ge-P	HF,15V,0,1A,0,25W,>200MHz	2a	Tix	(AF109R,AF139,AF239(S))
2N1404(A)	Ge-P	NF/S,25V,0,3A,0,15W,>4MHz	2a	USA,Tix	ASY76..77
2N1405	Ge-P	HF,30V,0,05A,0,075W,1100MHz	5g	Tix	AF139,AF239(S)
2N1406	Ge-P	HF,30V,0,05A,0,075W,1100MHz	5g	Tix	AF139,AF239(S)
2N1407	Ge-P	HF,30V,0,05A,0,075W,1100MHz	5g	Tix	AF139,AF239(S)
2N1408	Ge-P	NF/S,50V,0,2A,0,15W	2a	USA,Mot	ASY48,ASY77
2N1409(A)	Si-N	NF/S,30V,0,5A,0,6..0,8W,B>15	2a	USA	BC140..141,BC300..302,2N2218..19,++
2N141(/13)	Ge-P	NF-Tr/E,80V,0,6A		USA	—
2N1410(A)	Si-N	=2N1409(A): B>30	2a	USA	BC140..141,BC300..302,2N2218..19,++
2N1411	Ge-P	S,-/50V,0,025W,70MHz	37d	USA	—
2N1412(A)	Ge-P	NF/S-L,100V,15A,150W	38a	USA,Mot	2N2493
2N1413	Ge-P	NF/S,35V,0,5A,0,225W,B>25	2a(B=case)	USA,Mot	AC126,AC152..153,2SB324,2SB415
2N1414	Ge-P	=2N1413: B>34	2a(B=case)	USA,Mot	AC126,AC152..153,2SB324,2SB415
2N1415	Ge-P	=2N1413: B>53	2a(B=case)	USA,Mot	AC126,AC152..153,2SB324,2SB415

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2N1416	Ge-P	=2x2N223: gep	2x37e	Csr,Etc	→2N223
2N1417	Si-N	HF/S/Chopper, 15V, 0,05A, 0,15W	2a	USA	(BC168, BC183, BC238, BC548,++)
2N1418	Si-N	=2N1417: 30V	2e	USA,TO-5	(BC168, BC183, BC238, BC548,++)
2N1419	Ge-P	NF/S-L, 80V, 25A, 87W	23a	Cen	2N1652..53, 2N2286..87
2N142(/13)	Ge-N	NF-Tr/E, 60V, 0,8A		USA	—
2N1420(A)	Si-N	NF/S, 60V, 1A, 0,8..0,8W, >50MHz	2a	USA,EUR	BC140..141, BC300..302, 2N1990,++
2N1421	Si-N	S-L, 60V, 3A, 30W	49m	Tra	2N5002, 2N5004, 2N5284..85
2N1422	Si-N	S-L, 60V, 3A, 30W	23a	Tra	AL102..103, AUY19..20, 2N2144..46,++
2N1423	Si-N	S-L 60V, 3A, 60W	23a	Tra	AL102..103, AUY19..20, 2N2144..46,++
2N1424	Si-N	S-L, 60V, 3A, 60W	49m	Tra	2N5002, 2N5004, 2N5284..85
2N1425	Ge-P	HF, 24V, 10mA, 0,03W, >6MHz	1g	Rca	AF124..127, AF200
2N1426	Ge-P	HF, 24V, 10mA, 0,03W, >6MHz	1g	Rca	AF124..127, AF200
2N1427	Ge-P	HF/S, 8V, 0,05A, 0,025W, 60MHz	37d	USA	ASZ21, 2N705, 2N960..967
2N1428	Si-P	NF/S, 6V, 0,05A, 0,1W, >18MHz	2a	USA	BC213, BC258, BC308, BC558,++
2N1429	Si-P	=2N1428:	2a	USA	BC213, BC258, BC308, BC558,++
2N143(/13)	Ge-P	NF-Tr/E, 60V, 0,8A		USA	—
2N1430	Ge-P	S-L, 100V, 10A, 70W	23a	Gpd,Idi	AL100..101, AUY37, 2N2290, 2N2293
2N1431	Ge-N	NF/S, 20V, 0,1A, 0,18W	2e	Etc	AC127, AC176, AC187
2N1432	Ge-P	HF, 45V, 10mA, 0,1W	5g	Syl	AF124..127, AF200
2N1433	Ge-P	NF/S-L, 80V, 3,5A, 12W(Tc=75°), B>20	≈37b	Cbe	—
2N1434	Ge-P	=2N1433: B>45	≈37b	Cbs	—
2N1435	Ge-P	=2N1433: B>30	≈37b	Cbs	—
2N1436	Ge-P	S, 15V, 0,05A, 0,05W, <70/-ns	2a	Phc	ASZ21, 2N705, 2N960..87
2N1437	Ge-P	S-L, 100V, 3A, 23W	≈37b	Gpd,Stc	—
2N1438	Ge-P	S-L, 100V, 3A, 23W	≈37b	Gpd,Stc	—
2N1439	Si-P	Uni, 50V, 0,1A, 0,4W, >1MHz, β=9	2a	USA	BC212, BC257, BC307, BC557,++
2N144(/13)	Ge-N	NF-Tr/E, 80V, 0,5A		USA	—
2N1440	Si-P	=2N1439: 60V, β=16	2a	USA	BC212, BC258, BC266, BC556,++
2N1441	Si-P	=2N1439: β=27	2a	USA	BC212, BC257, BC307, BC557,++
2N1442	Si-P	=2N1439: β=43	2a	USA	BC212, BC257, BC307, BC557,++
2N1443	Si-P	=2N1439: β=65	2a	USA	BC212, BC257, BC307, BC557,++
2N1444	Si-N	NF/S, 60V, 0,25A, 0,5W, <250/250ns	2a	Wee	BC140..141, BC300..302, 2N2218..19,++
2N1445	Si-N	NF/S, 120V, 0,75A, 0,8W	2a	USA	BC300, 2N1893, 2SC959, 2SC2105,++
2N1446	Ge-P	NF/S, 45V, 0,4A, 0,2W, β=30	2e	USA	2N1189..90, 2SB405ST
2N1447	Ge-P	=2N1446: β=45	2a	USA	2N1189..90, 2SB405ST
2N1448	Ge-P	=2N1446: β=65	2a	USA	2N1189..90, 2SB405ST
2N1449	Ge-P	=2N1446: β=60	2e	USA	2N1189..90, 2SB405ST
2N145	Ge-N	HF, 20V, 300mA, 0,055W, β=30	2e	Csr,Etc	—
2N1450	Ge-P	S, 30V, 0,1A, 0,12W, <200/170ns	2a	USA	2N2955..57
2N1451	Ge-P	NF, 45V, 0,4A, 0,2W, B>20	2a	USA	2N1189..90, 2SB405ST
2N1452	Ge-P	=2N1451: B>30	2a	USA	2N1189..90, 2SB405ST
2N1453	Ge-P	NF/S-L, 30V, 5A, 43W, B>40	≈37b	Cbs	—
2N1454	Ge-P	=2N1453: B>70	≈37b	Cbs	—
2N1455	Ge-P	=2N1453: 60V	≈37b	Cbs	—
2N1456	Ge-P	=2N1453: 60V, B>70	≈37b	Cbs	—
2N1457	Ge-P	=2N1453: 60V	≈37b	Cbs	—
2N1458	Ge-P	=2N1453: 60V, B>70	≈37b	Cbs	—
2N146	Ge-N	=2N145: β=50	2a	Etc	—
2N1461	Ge-P	=2N1453:	≈37b	Cbs	—
2N1462	Ge-P	=2N1453: B>70	≈37b	Cbs	—
2N1463	Ge-P	=2N1453: 60V	≈37b	Cbs	—
2N1464	Ge-P	=2N1453: 60V, B>70	≈37b	Cbs	—
2N1465	Ge-P	NF/S-L, 120V, 3A, 20W	≈37b	USA	—
2N1466	Ge-P	=2N1465	≈37b	USA	—
2N1468	Si-N	Avalanche-S	2a	Ray	—
2N1469	Si-P	Uni, 40V, 0,1A, 0,25W, >2MHz	2a	USA	BC212, BC257, BC307, BC557,++
2N147	Ge-N	=2N145: β=70	2e	Etc	—
2N1470	Si-N	NF/S-L, 60V, 3A, 55W	23a	Csr,Idi	BD245A, BDV91, BDX91, 2N4914..15,++
2N1471	Ge-P	S, 12V, 0,2A, 0,2W, >3MHz	2a	USA	2N705(A), 2N960..967, 2N2955..57
2N1472	Si-N	S, 25V, 0,1A, 0,15W, 140MHz	2a	USA	BSW41, BSY62..63, 2N706A, 2N708,++
2N1473	Ge-N	NF/S, 40V, 0,4A, 0,25W, 8MHz	2a	USA	—
2N1474(A)	Si-P	sym, 60/60/60V, 0,1A, 0,25W	2a	USA	—
2N1475	Si-P	sym, 60/60/60V, 0,1A, 0,25W	2a	USA	—
2N1476	Si-P	sym, 100/100/100V, 0,1A, 0,25W	2a	USA	—
2N1477	Si-P	sym, 100/100/100V, 0,1A, 0,25W	2a	USA	—
2N1478	Ge-P	HF/S, 30V, 0,5A, 0,25W, 8MHz	2a	USA	ASY76..77

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2N1479	Si-N	NF/S, 60V, 1,5A, 5W(Tc=25°), B>20	2a	USA,Rca	BCX40, BSS15..16, 2N5320..21,++
2N148	Ge-N	HF, 16V, 300mA, 0,065W, B=35	2a	Tix	—
2N1480	Si-N	=2N1479: 100V	2a	USA,Rca	BCX40, BSS15, BSV84, 2N5320,++
2N1481	Si-N	=2N1479: B>35	2a	USA,Rca	BCX40, BSS15..16, 2N53+F1080620..21,++
2N1482	Si-N	=2N1479: 100V, B>35	2a	USA,Rca	BCX40, BSS15, BSV84, 2N5320,++
2N1483	Si-N	NF/S-L, 60V, 3A, 25W(Tc=25°), B>20	2a	USA,Rca	(BD241A BD535, BD539A, BD935,++)
2N1484	Si-N	=2N1483: 100V	2a	USA,Rca	(BD241C, BD539C, BD937, 2SD712,++)
2N1485	Si-N	=2N1483: B>35	2a	USA,Rca	(BD241A BD535, BD539A, BD935,++)
2N1486	Si-N	=2N1483: 100V, B>35	2a	USA,Rca	(BD241C, BD539C, BD937, 2SD712,++)
2N1487	Si-N	NF/S-L, 60V, 6A, 75W, B>15	23a	USA,Rca,Tix	BD245A, BDV91, BDX91, 2N4914..15,++
2N1488	Si-N	=2N1487: 100V	23a	USA,Rca,Tix	BD245C, BDV95, BDX95, 2N5758..60,++
2N1489	Si-N	=2N1487: B>25	23a	USA,Rca,Tix	BD245A, BDV91, BDX91, 2N4914..15,++
2N148A	Ge-N	=2N148: 32V	3a		—
2N149	Ge-N	HF, 16V, 5mA, 0,065W, B=38	≈1a	Tix	—
2N1490	Si-N	=2N1487: 100V, B>25	23a	USA,Rca,Tix	BD245C, BDV95, BDX95, 2N5758..60,++
2N1491	Si-N	VHF, 30V, 0,1A, 0,5W, 250MHz	2a	USA,Rca	BFW16..17
2N1492	Si-N	VHF, 60V, 0,1A, 0,5W, 275MHz	2a	USA,Rca	—
2N1493	Si-N	VHF, 100V, 0,1A, 0,5W, 300MHz	2a	USA,Rca	—
2N1494(A)	Ge-P	S, 20V, 0,5A, 0,75W, >110MHz	49m	Mot,Sty	2N2096
2N1495(A)	Ge-P	S, 40V, 0,5A, 0,3W, >150MHz	2a	Mot,Sty	2N2100
2N1496	Ge-P	=2N1495: 0,5W	49m	Mot,Sty	2N2097
2N1499(A)	Ge-P	S, 20V, 0,1A, 0,08W, >100MHz	2a	USA	2N2955..57
2N1499B	Ge-P	S, 30V, 0,1A, 0,075W, >150MHz	2a		2N2955..57
2N149A	Ge-N	=2N149: 32V	≈1a		—
2N150	Ge-N	HF, 20V, 300mA, 0,065W, B=41	2a	Tix	—
2N1500(/18)	Ge-P	S, 30V, 0,1A, 0,075W, >150MHz	2a	USA	ASZ21, 2N705, 2N960..67, 2N2955..57
2N1501	Ge-P	S-L, 60V, 3,5A, 34W	≈37b	USA	—
2N1502	Ge-P	=2N1501: 40V	≈37b	USA	—
2N1504(/10)	Ge-P	S-L, 60V, 3A, 23W	≈37b	Gpd,Stc	—
2N1505	Si-N	HF-O/Tr, 50V, 0,5A, PQ=1,1W(70MHz)	2a	USA	BFX55
2N1506	Si-N	HF-O/Tr, 60V, 0,5A, PQ=1,3W(70MHz)	2a	USA	BFX55
2N1506A	Si-N	=2N1506: 60V	2a		(BFX55)
2N1507	Si-N	NF/S, 60V, 1A, 0,6W, >50MHz	2a	USA,Tix	BC140..141, BC300..302, 2N1990,++
2N1508	Si-N	=2N1509: 100V	2a	Sty	BC141, BC300, BSW39, 2N1990,++
2N1509	Si-N	NF/S, 60V, 1A, 1W	2a	Sty	BC140..141, BC300..302, 2N2218..19,++
2N150A	Ge-N	=2N150: 32V	2a		—
2N151	Ge-P			old	—
2N1510	Ge-N	NF/S, 20V, 0,2A, 0,075W	2a	USA	—
2N1511	Si-N	S-L, 60V, 6A, 75W, B>15	38a	USA	(BD245A, BDV91, BDX91, 2N4914..15,++)
2N1512	Si-N	=2N1511: 100V	38a	USA	(BD245C, BDV95, BDX95, 2N5758..60,++)
2N1513	Si-N	=2N1511: B>25	38a	USA	(BD245A, BDV91, BDX91, 2N4914..15,++)
2N1514	Si-N	=2N1511: 100V, B>25	38a	USA	(BD245C, BDV95, BDX95, 2N5758..60,++)
2N1515	Ge-P	HF, 20V, 10mA, 0,083W, 70MHz	1g	Amp	AF124..126, AF200
2N1516	Ge-P	HF, 25V, 10mA, 0,063W, 70MHz	1g	Amp	AF124..126, AF200
2N1517	Ge-P	HF, 20V, 10mA, 0,063W, 70MHz	1g		AF124..126, AF200
2N1517A	Ge-P	=2N1517: 40V, 0,1W	1g		AF124..128, AF200
2N1518	Ge-P	NF/S-L, 50V, 25A, 87,5W	38a	USA	2N2153..55, 2N2157..59
2N1519	Ge-P	=2N1518: 60V	38a	USA	2N2155, 2N2159
2N152	Ge-P			old	—
2N1520	Ge-P	NF/S-L, 50V, 35A, 87,5W	38a	USA	2N2153..55, 2N2157..59
2N1521	Ge-P	=2N1520: 60V	38a	USA	2N2155, 2N2159
2N1522	Ge-P	NF/S-L, 50V, 50A, 87,5W	38a	USA	2N4049..50, 2N4052..53
2N1523	Ge-P	=2N1522: 60V	38a	USA	2N4050, 2N4053
2N1524	Ge-P	HF, 24V, 10mA, 0,08W, 33MHz	2a	USA	AF124..127, AF200
2N1524/33	Ge-P	=2N1524: 0,12W	5g		AF124..127, AF200
2N1525	Ge-P	HF, 24V, 10mA, 0,08W, 33MHz	1a	USA	AF124..127, AF200
2N1526	Ge-P	HF, 24V, 10mA, 0,08W, 33MHz	2a	USA	AF124..127, AF200
2N1526/33	Ge-P	=2N1526: 0,12W	5g		AF124..127, AF200
2N1527	Ge-P	HF, 24V, 10mA, 0,08+C10693W, 33MHz	1a	USA	AF124..127, AF200
2N1528	Si-N	HF/S, 25V, 0,02A, 0,15W, 20MHz	2a	Ray	BC168, BC183, BC238, BC548,++
2N1529(A)	Ge-P	NF/S-L, 40V, 5A, 106W, B>20	23a	USA,Mot,Tix	2N3811..18
2N153	Ge-P			old	—
2N1530(A)	Ge-P	=2N1529: 60V	23a	USA,Mot,Tix	2N3812, 2N3814, 2N3615..18
2N1531(A)	Ge-P	=2N1529: 60V	23a	USA,Mot,Tix	2N3615..18
2N1532(A)	Ge-P	=2N1529: 100V	23a	USA,Mot,Tix	2N3816, 2N3618
2N1533(A)	Ge-P	=2N1529: 120V	23a	USA,Mot,Tix	—

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2N1534(A)	Ge-P	NF/S-L, 40V, 5A, 106W, B>35	23a	USA,Mot,Tix	2N3611..18
2N1535(A)	Ge-P	=2N1534: 60V	23a	USA,Mot,Tix	2N3612, 2N3614, 2N3615..18
2N1536(A)	Ge-P	=2N1534: 60V	23a	USA,Mot,Tix	2N3615..18
2N1537(A)	Ge-P	=2N1534: 100V	23a	USA,Mot,Tix	2N3616, 2N3618
2N1538(A)	Ge-P	=2N1534: 120V	23a	USA,Mot,Tix	—
2N1539(A)	Ge-P	NF/S-L, 40V, 5A, 106W, B>50	23a	USA,Mot,Tix	2N3611..18
2N1540	Ge-P			old	—
2N1540(A)	Ge-P	=2N1539: 60V	23a	USA,Mot,Tix	2N3612, 2N3614, 2N3615..18
2N1541(A)	Ge-P	=2N1539: 60V	23a	USA,Mot,Tix	2N3615..18
2N1542(A)	Ge-P	=2N1539: 100V	23a	USA,Mot,Tix	2N3618, 2N3618
2N1543(A)	Ge-P	=2N1539: 120V	23a	USA,Mot,Tix	—
2N1544(A)	Ge-P	NF/S-L, 40V, 5A, 106W, B>75	23a	USA,Mot,Tix	(2N3611..18)
2N1545(A)	Ge-P	=2N1544: 60V	23a	USA,Mot,Tix	(2N3612, 2N3614, 2N3615..18)
2N1546(A)	Ge-P	=2N1544: 80V	23a	USA,Mot,Tix	(2N3615..18)
2N1547(A)	Ge-P	=2N1544: 100V	23a	USA,Mot,Tix	(2N3616, 2N3618)
2N1548(A)	Ge-P	=2N1544: 120V	23a	USA,Mot,Tix	—
2N1549(A)	Ge-P	NF/S-L, 40V, 15A, 106W, B>10	23a	USA,Mot,Tix	2N1651..58, 2N2285..87
2N155	Ge-P	NF/S-L, 30V, 3A, 20W	23a	USA	AD149, AUY19..20, 2N2137, 2N2142,++
2N1550(A)	Ge-P	=2N1549: 60V	23a	USA,Mot,Tix	2N1651..53, 2N2285..87
2N1551(A)	Ge-P	=2N1549: 60V	23a	USA,Mot,Tix	2N1652..53, 2N2286..87
2N1552(A)	Ge-P	=2N1549: 100V	23a	USA,Mot,Tix	2N1652..53, 2N2286..87
2N1553(A)	Ge-P	NF/S-L, 40V, 15A, 106W, B>30	23a	USA,Mot,Tix	2N1651..53, 2N2285..87
2N1554(A)	Ge-P	=2N1553: 60V	23a	USA,Mot,Tix	2N1651..53, 2N2285..87
2N1555(A)	Ge-P	=2N1553: 80V	23a	USA,Mot,Tix	2N1652..53, 2N2286..87
2N1556(A)	Ge-P	=2N1553: 100V	23a	USA,Mot,Tix	2N1652..53, 2N2286..87
2N1557(A)	Ge-P	NF/S-L, 40V, 15A, 106W, B>50	23a	USA,Mot,Tix	2N1651..53, 2N2285..87
2N1558(A)	Ge-P	=2N1557: 60V	23a	USA,Mot,Tix	2N1651..53, 2N2285..87
2N1559(A)	Ge-P	=2N1557: 80V	23a	USA,Mot,Tix	2N1652..53, 2N2286..87
2N156	Ge-P	=2N155: 25W		USA	(AD149, AUY19..20, 2N2137, 2N2142,++)
2N1560(A)	Ge-P	=2N1557: 100V	23a	USA,Mot,Tix	2N1652..53, 2N2286..87
2N1561	Ge-P	VHF-A/Tr, 25V, 0,25A, PQ>0,5W(160MHz)	≈2a	Mot	(2N1692)
2N1562	Ge-P	VHF-A/Tr, 25V, 0,25A, PQ>0,4W(160MHz)	≈2a	Mot	(2N1693)
2N1564	Si-N	NF, 60V, 0,05A, 0,6W, >30MHz	2a	USA,Tix	BC140..141, BC300..301, 2N1889..90,++
2N1565	Si-N	NF, 60V, 0,05A, 0,6W, >60MHz	2a	USA,Tix	BC140..141, BC300..301, 2N1889..90,++
2N1566	Si-N	NF, 80V, 0,05A, 0,6W, >60MHz	2a	USA,Tix	BC140..141, BC300..301, 2N1889..90,++
2N1566A	Si-N	=2N1566: 0,1A, >100MHz	2a		BC140..141, BC300..301, 2N1889..90,++
2N157	Ge-P	NF/S-L, 60V, 3A, 20W	23a	USA	AUY19..20, 2N2139..41, 2N2144..46,++
2N1572	Si-N	NF, 125V, 0,05A, 0,6W, >30MHz	2a	USA,Tix	BC300, 2N1893(A), 2SD755..756(A),++
2N1573	Si-N	NF, 125V, 0,05A, 0,6W, >60MHz	2a	USA,Tix	BC300, 2N1893(A), 2SD755..756(A),++
2N1574	Si-N	NF, 125V, 0,05A, 0,6W, >60MHz	2a	USA,Tix	BC300, 2N1893(A), 2SD755..756(A),++
2N157A	Ge-P	=2N157: 90V	23a		AUY28, AUY34, 2N2141, 2N2146,++
2N158	Ge-P	=2N157: 25W		USA	(AUY19..20, 2N2139..41, 2N2144..46,++)
2N1585	Ge-N	HF, 25V, 0,1A, 0,3W, 400MHz	2a	Cen	—
2N1586	Si-N	Uni, 15V, 0,025A, 0,125W, >5MHz	≈1a	USA,Tix	BC168, BC183, BC236, BC548,++
2N1587	Si-N	40V, 60mA	5e	USA,Tix	BC188, BC183, BC236, BC548,++
2N1588	Si-N	=2N1587: 60V	5e	USA,Tix	BC174, BC182, BC190, BC546,++
2N1589	Si-N	Uni, 35V, 0,5A, 0,125W, >5MHz	5c	USA,Tix	BC188, BC183, BC283, BC548,++
2N158A	Ge-P	=2N157: 90V, 25W			(AUY28, AUY34, 2N2141, 2N2146,++)
2N159	Ge-P	S, 50V, 0,01A, 0,06W	2a	Spr	(ASY77)
2N1590	Si-N	=2N1587: 40V	5e	USA,Tix	BC188, BC183, BC236, BC546,++
2N1591	Si-N	=2N1587: 60V	5e	USA,Tix	BC174, BC182, BC190, BC546,++
2N1592	Si-N	Uni, 35V, 0,05A, 0,125W, >5MHz	5c	USA,Tix	BC168, BC183, BC236, BC546,++
2N1593	Si-N	=2N1591: 30V	5e	USA,Tix	BC168, BC183, BC236, BC546,++
2N1594	Si-N	=2N1591: 60V	5e	USA,Tix	BC174, BC182, BC190, BC546,++
2N1595	50Hz-Thy	50V, 1A(Tc=80°), Igt/Ih<10/5mA	2a	USA,Tag,Tho	BTX30/50, T1N100A, TAG1-50, S2600B++
2N1595A	50Hz-Thy	50V, 1A(Tc=80°C), Igt/Ih<2/5mA	2a		TAG2-50, MCR1906-2, TAG614-100
2N1596	50Hz-Thy	=2N1596: 100V	2a		BTX30/100, T1N100A, TAG1-100, S2600B,++
2N1596A	50Hz-Thy	=2N1595A: 100V	2a		TAG2-100, MCR1906-3, TAG614-100
2N1597	50Hz-Thy	=2N1596: 200V	2a		BTX30/200, T1N200A, TAG1-200, S2600B,++
2N1597A	50Hz-Thy	=2N1595A: 200V	2a		TAG2-200, MCR1906-4, TAG614-200
2N1598	50Hz-Thy	=2N1596: 300V	2a		BTX30/300, T1N300A, TAG1-300, S2600D,++
2N1598A	50Hz-Thy	=2N1595A 300V	2a		TAG2-300, MCR1906-5, TAG614-300
2N1599	50Hz-Thy	=2N1596: 400V	2a		BTX30/400, T1N400A, TAG1-400, S2600D,++
2N1599A	50Hz-Thy	=2N1595A: 400V	2a		TAG2-400, MCR1906-6, TAG614-400
2N160(A)	Si-N	Uni, 40V, 0,6A, 0,15W, B>9	5e	USA	BC167, BC182, BC237, BC547,++
2N1605	Ge-N	NF/S, 25V, 0,1A, 0,15W, >4MHz	2a	USA,Tix	ASY28..29, ASY73..75

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2N1605A	Ge-N	=2N1605: 40V	2a		—
2N1606	Si-P	S, 10/10/10V, 0,05A, 0,1W, >7,2MHz	2a	Phc	—
2N1607	Si-P	S, 10/10/10V, 0,05A, 0,1W, >10MHz	2a	Phc	—
2N1606	Si-P	S, 10/10/10V, 0,05A, 0,1W, >25MHz	2a	Phc	—
2N1609	Ge-P	NF/S-L, 60V, 1,5A, 4,5W, B>30	43m	Del	—
2N161(A)	Si-N	=2N160: B>19	5e	USA	BC167, BC182, BC237, BC547, ++
2N1610	Ge-P	=2N1609: B>50	43m	Del	—
2N1611	Ge-P	=2N1609: 60V	43m	Del	—
2N1612	Ge-P	=2N1609: 60V, B>50	43m	Del	—
2N1613(S)	Si-N	Uni, 75V, 0,5A, 0,8W, >60MHz	2a	USA,EUR	BC140..141, BC300..301, 2N1990, ++
2N1613A,L	Si-N	=2N1613: 1A, 1W	2a		BC140..141, 2N1990, 2N2102, 2N2405, ++
2N1613B	Si-N	=2N1613: 120V, 1A, 1W	2a		2N2102, 2N2405, 2N3019..20
2N1614	Ge-P	NF/S, 65V, 0,3A, 0,24W, >0,5MHz	1a	USA	ASY48, ASY77
2N1615	Si-N	NF/S, 100V, 0,2A, 0,6W, >2MHz	2a	USA	BC141, BC300, 2N1889..90, 2N1893(A), ++
2N1616(/I)	Si-N	S-L, 60V, 5A, 60W, >3MHz	49m	USA,Tho	2N3467..92
2N1616A	Si-N	=2N1616: 7,5A, 85W	49m		2N3487..92
2N1617(/I)	Si-N	S-L, 60V, 5A, 60W, >3MHz	49m	USA,Tho	2N3487..92
2N1617A	Si-N	=2N1617: 7,5A, 65W	49m		2N3487..92
2N1618A	Si-N	S-L, 100V, 5A, 60W, >3MHz	49m	USA,Tho	2N3488..69, 2N3491..92
2N1616A	Si-N	=2N1618: 7,5A, 65W	49m		2N3488..89, 2N3491..92
2N1619	Si-N	S-L, 60V, 5A, 60W, >3MHz	49m	USA,Tho	2N3487..92
2N162(A)	Si-N	=2N1592: B>19	5c	USA	BC167, BC162, BC237, BC547, ++
2N1620(/I)	Si-N	S-L, 100V, 5A, 60W, >3MHz	49m	USA,Tho	2N3488..89, 2N3491..92
2N1622	Ge-N	NF/S, 90V, 0,12W, 1MHz	2a	USA	—
2N1623	Si-P	Uni, 50V, 0,05A, 0,25W	2a	USA	(BC212, BC257, BC307, BC557, ++)
2N1624	Ge-N	NF/S, 25V, 0,15W, >5MHz	2a	USA	ASY28..29, ASY73..75
2N163(A)	Si-N	=2N160: B>39	5e	USA	BC167, BC162, BC237, BC547, ++
2N1631	Ge-P	HF, 34V, 10mA, 0,08W, 45MHz	1a	USA	AF124..128, AF200
2N1632	Ge-P	=2N1631:	2e	USA	AF124..128, AF200
2N1633	Ge-P	HF, 34V, 10mA, 0,08W, 40MHz	1a	USA	AF124..126, AF200
2N1634	Ge-P	=2N1633:	2a	USA	AF124..128, AF200
2N1635	Ge-P	HF, 34V, 10mA, 0,08W, 45MHz	1a	USA	AF124..126, AF200
2N1636	Ge-P	=2N1635:	2a	USA	AF124..126, AF200
2N1637	Ge-P	HF, 34V, 10mA, 0,08W, 45MHz	2a	USA	AF124..128, AF200
2N1637/33	Ge-P	=2N1637: 0,12W	5g		AF124..128, AF200
2N1836	Ge-P	HF, 35V, 10mA, 0,08W, 40MHz	2a	USa	AF124..126, AF200
2N1638/33	Ge-P	=2N1638: 0,12W	5g		AF124..126, AF200
2N1639	Ge-P	HF, 34V, 10mA, 0,08W, 45MHz	2a	USA	AF124..128, AF200
2N1639/33	Ge-P	=2N1639: 0,12W	2a		AF124..126, AF200
2N164(A)	Ge-N	NF/HF, 15V, 0,03A, 0,06W, >4MHz	2a	Csr,Etc	ASY28..29
2N1640	Si-P	Chopper, 30V, 0,05A, 0,25W, B>6	2a	SSi,Tdy	(2N2948)
2N1641	Si-P	Chopper, 30V, 0,05A, 0,25W, B>10	2a	SSi,Tdy	(2N2946)
2N1642	Si-P	Chopper, 30V, 0,05A, 0,25W, B>15	2a	SSi,Tdy	(2N2946)
2N1643	Si-P	Chopper, 25V, 0,05A, 0,25W, B>10	2a	SSi,Tdy	(2N2948)
2N1644(A)	Si-N	NF/S, 60V, 0,6W, >50MHz	2a	USA	BC140..141, BC300..302, 2N3053, ++
2N1645	Ge-P	HF-Tr, -/20V, 0,3A, 1W, 600MHz	≈2a	Wes	—
2N1646	Ge-P	HF/S, 15V, 0,05A, 0,15W	2a	USA,Tix	AF106, AF109R, AF306
2N1647	Si-N	S-L, 80V, 5A, 40W, >3MHz, B>15	≈21	USA	2N5002, 2N5004, 2N5294..65, (BD243B, ++)
2N1648	Si-N	=2N1647: 120V	≈21	USA	2N5284..85, (BD243C, BD539D, ++)
2N1649	Si-N	S-L, 80V, 5A, 40W, >3MHz, B>30	≈21	USA	2N5002, 2N5004, 2N5294..85, (BD243B, ++)
2N185	Ge-N	NF/HF, 15V, 0,02A, 0,06W, 5MHz	2a	Csr,Etc	ASY28..29
2N1650	Si-N	=2N1647: 120V	≈21	USA	2N5264..85, (BD243C, BD539D, ++)
2N1651	Ge-P	NF/S-L, 60V, 25A, 106W	23a	USA, Mot	2N2285..67
2N1652	Ge-P	=2N1651: 100V	23a	USA, Mot	2N2286..67
2N1653	Ge-P	=2N1851: 120V	23a	USA, Mot	2N2287
2N1654	Si-P	Uni, 100V, 0,05A, 0,25W, B>20	2a	USA	BF398, 2SA893(A), 26A970, 2SA1285(A), ++
2N1655	Si-P	=2N1654: 125V, B>10	2a	USA	BF398, 2SA893(A), 2SA970, 2SA1285(A), ++
2N1656	Si-P	=2N1854: 125V, B>20	2a	USA	BF398, 28A893(A), 2SA970, 2SA1285(A), ++
2N1657	Si-N	NF/S-L, 60V, 2A, 55W		Ray,Tix	2N1722..23, (BD241, BD535, BD935, ++)
2N1656(/13)	Ge-P	NF/S-L, 80V, 1A, 15W	≈37	USA	—
2N1659(/13)	Ge-P	=2N1658: 60V	≈37	USA	—
2N166	Ge-N	NF/HF, 6V, 0,02A, 0,025W, 5MHz	2a	Csr,Etc	ASY28..29
2N1660	Si-N	NF/S-L, 60V, 2A, 65W		Ray,Tix	2N1722..23, (BD239A, BD241A, BD935++)
2N1661	Si-N	=2N1660: 60V		Ray,Tix	2N1722..23, (BD239B, BD241B, BD937++)
2N1662	Si-N	=2N1660: 100V		Ray,Tix	2N1722..23, (BD239C, BD241C, BD937++)
2N1663	Si-N	S, 20V, 0,1A, 0,15W, -/65na	2a	Phc	BSV89..92, BSX92..93, 2N2368..69(A), ++

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2N1664	Ge-P	NF/S,45V,0,2A,0,2W,5MHz	2a	USA	ASY48,ASY76..77
2N1665	Ge-P	HF,15V,0,05A,0,15W	2a	USA	(AF109R,AF139,AF239(S))
2N1666	Ge-P	S-L,80V,6A,30W,B>15	23a	Cen,Gpd	AL102..103,AUY28,2N3615..18,++
2N1667	Ge-P	S-L,80V,6A,30W,B>35	23a	Cen,Gpd	AL102..103,AUY28,2N3615..18,++
2N1666	Ge-P	S-L,80V,6A,30W,B>20	23a	Cen,Gpd	AL102..103,AUY28,2N8615..18,++
2N1669	Ge-P	S-L,80V,6A,30W,B>20	23a	Cen,Gpd	AL102..103,AUY28,2N6615..18,++
2N167(A)	Ge-N	S,20V,0,3A,0,065W	2a	Csr,Etc	ASY28
2N1670	Ge-P	NF/S,100V,0,12W,>10MHz	2a	USA	ACY39,2N2042..43
2N1671A	UJT-P	Ip<25μA,Iv>8mA	5e,2l	Gen,Tho,Tix	—
2N1671AP	UJT-P	=2N1671A: Ip<12μA	5e,2l		—
2N1671AX	UJT-P	=2N1671A	5e,2l		—
2N1871B	UJT-P	=2N1671A: Ip<6μA	5a,2l		—
2N1671BX	UJT-P	=2N1671A: Ip<8μA	5e,2l		—
2N1671C	UJT-P	=2N1671A Ip<2μA	5a,2l		2N2647
2N1671CX	UJT-P	=2N1871A: Ip<2μA	5a,2l		2N2647
2N1672(A)	Ge-N	NF/S,40V,0,12W,>2MHz	2a	USA	—
2N1873	Ge-P	HF,35V,10mA,0,06W,5MHz	5g	Cen	AF124..127,AF200
2N1674	Si-N	Uni,45V,0,025A,0,2W,>20MHz	2a	Sem,Tra	BC167,BC182,BC237,BC+F11046547,++
2N1875	Si-N	S-L,100V,10A,100W,>120MHz	=2a	Wes	(23C2527)
2N1876	Si-P	Chopper,4,5/4,5/4,5V,0,05A,0,1W	2a	USA	—
2N1677	Si-P	Chopper,4,5/4,5/4,5V,0,06A,0,1W	2a	USA	—
2N1878	Ge-P	HF/S,60V,0,12W,>25MHz	2a	USA	AF118
2N1679	Si-N	NF-Tr,100V,1A,1W,>50MHz	2a	Sty,Tix	BC141,BSW39,2N1990,2SC1069,++
2N166(A)	Ge-N	HF,20V,0,3A,0,065W	2a	Csr,Etc	ASY28..29
2N1880	Si-N	=2N1679: 80V	2a	Sty,Tix	BC140..141,BSW27..28,2SC1069,++
2N1681	Ge-P	NF,30V,0,2A,0,18W,>5MHz	2a	USA	ASY28,ASY76..77
2N1682	Si-N	HF/S,25V,0,5W,>200MHz	2a	USA	BFX98..97,BSY58,2N2218..19(A),++
2N1683	Ge-P	HF/S,13V,0,1A,0,15W,80MHz	2a	USA	ASZ21,2N705,2N960..67
2N1684	Ge-P	NF/S,25V,0,1A,0,1W	2a	Syl	AC125..126,AC151,2SB54,2SB56
2N1685	Ge-N	NF/S,25V,0,1A,0,1W	2a	Syl	AC127,AC176,AC187,ASY28..29
2N1886	GTO-Thy	30V,1A,Igt/Ih<1/<5mA	2a	Sem,Sld	—
2N1687	GTO-Thy	=2N1666: 60V	2a		—
2N1688	GTO-Thy	=2N1886: 100V	2a		—
2N1689	GTO-Thy	=2N1666: 200V	2a		—
2N169(A)	Ge-N	HF,20V,0,3A,0,065W	2a	Csr,Etc	ASY28..29
2N1690	Si-N	S-L,80V,0,5A,40W		USA,Tix	(BD189,BD237,BD239B,BD241B,++)
2N1691	Si-N	=2N1690: 120V		USA,Tix	(BD239C,BD241C,BD939,28C2481,++)
2N1892	Ge-P	VHF-A/Tr,25V,0,25A,PO>0,5W(180MHz)	49a	USA,Mot	(2N1561)
2N1693	Ge-P	VHF-A/Tr,25V,0,25A,PO>0,4W(160MHz)	49a	USA,Mot	(2N1562)
2N1694	Ge-N	NF/S,20V,0,025A,0,075W,9MHz	2a	USA	(ASY28..29,ASY73..75)
2N1699	Ge-P	HF,40V,0,1W,100MHz		Syl	AF108,AF109R,AF306
2N170	Ge-N	HF,20V,0,3A,0,025W	2a	Csr,Etc	ASY28..29
2N1700	Si-N	NF/S,60V,1A,5W(Tc=25°)	2a	USA,Fer,Rca	BC140..141,BSX45..47,2N8107..10,++
2N1701	Si-N	NF/S-L,60V,2,5A,25W(Tc=25°)	2a	USA,Rca	(BD177,BD239A,BD437,BD935,++)
2N1702	Si-N	NF/S-L,80V,5A,75W	23a	USA,Fer,Rca	BD245A,BDV91,BDX91,2N4914..15,++
2N1703	Si-N	=2N1702:	38a	USA,Rca	(BD245A,BDV91,BDX91,2N4914..15,++)
2N1704	Si-N	Uni,45V,0,05A,0,5W,5MHz	2a	Csr,Etc	BC140..141,BC300..302,2N3053,++
2N1705	Ge-P	NF-Tr,18V,0,4A,0,2W,4MHz	2a	USA,Mot	AC128,AC152..153,AC188
2N1706	Ge-P	NF-Tr,25V,0,4A,0,2W,3MHz	2a	USA,Mot	AC128,AC152..153,AC188
2N1707	Ge-P	NF-Tr,30V,0,4A,0,2W,3MHz	2a	USA,Mot	AC128,AC152..153,AC188
2N1706	Si-N	S,25V,0,2A,0,3W,<40/75ns	2a	USA,Fer,Mot	BSS11..12,BSX19..20,2N2368..69(A),++
2N1708A	Si-N	=2N1708: 40V,0,5A	5g		BSS10,BSX28,BSX39,2N3+F10959281
2N1709	Si-N	HF-O/Tr,75V,1,2A,13W,100MHz	2a	USA	(BD139,BD230,2SC1398,2SC2690,++)
2N1710	Si-N	=2N1709: 80V	2a	USA	(BD137,BD228,2SC1398,2SC2890,++)
2N1711(S)	Si-N	Uni,75V,0,5A,0,8W,>70MHz	2a	USA,EUR	BC140..141,BC300..301,2N1990,++
2N1711A,L	Si-N	=2N1711: 1A,1W	2a		BC140..141,2N1990,2N2102,2N2405,++
2N1711B	Si-N	=2N1711: 120V,1A,1W	2a		2N2102,2N2405,2N3019..20
2N1713	Ge-P	HF,30V,10mA,0,08W,>100MHz	1g	Rca,Sty	AF106,AF109R,AF306
2N1714	Si-N	Uni,90V,0,75A,0,8W,>16MHz,B>20	2a	USA,Tix	BC141,BSS42..43,BSX46..47,2N5320++
2N1715	Si-N	=2N1714: 150V	2a	USA,Tix	BSS43,BSW66
2N1716	Si-N	Uni,90V,0,75A,0,8W,>16MHz,B>40	2a	USA,Tix	BC141,BSS42..43,BSX46..47,2N5320++
2N1717	Si-N	=2N1714: 150V,B>40	2a	USA,Tix	BSS43,BSW66
2N1716	Si-N	=2N1714:	49m	USA,Tix	(BD139,BD230,BD237,BD443,++)
2N1719	Si-N	=2N1715:	49m	USA,Tix	(BD443A,BD524,2SC2481,2SC2890A,++)
2N172	Ge-N	HF,20V,300mA,0,065W	2a	Csr,Etc	—
2N1720	Si-N	=2N1716:	49m	USA,Tix	(BD139,BD230,BD237,BD443,++)

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2N1721	Si-N	=2N1717	49m	USA,Tix	(BD443A,BD524,2SC2481,2SC2690A,++)
2N1722(/1)	Si-N	S-L,120V,5A,100W,B>20		USA,Tix	(BD245C,BD545D,2SD718,2SD896,++)
2N1722A(/1)	Si-N	=2N1722:180V			(BD245E,2SD751)
2N1723	Si-N	=2N1722:B>50		USA,Tix	(BD245C,BD545D,2SD718,2SD896,++)
2N1724	Si-N	S-L,120V,5A,100W,B>20	49m	USA,Mot,Tix	2N3489,2N3492
2N1724A	Si-N	=2N1724:180V	49m		2N5542
2N1725	Si-N	=2N1724:B>50	49m	USA,Mot,Tix	2N3489,2N3492
2N1726	Ge-P	HF,20V,0,05A,0,06W	2a	Etc,Spr	AF124..128,AF200
2N1727	Ge-P	HF,20V,0,05A,0,06W	2a	Etc,Spr	AF124..126,AF200
2N1728	Ge-P	HF,20V,0,05A,0,06W	2a	Etc,Spr	AF124..128,AF200
2N1729	Ge-P	NF/S,25V,0,3A,0,15W,<300/600ns	2a(B=case)	USA	ASY26..27,ASY76..77
2N173	Ge-P	NF/S-L,80V,15A,170W	38a	Del,Mot,++	2N1961,2N2076,2N2080,2N2491..93
2N1730	Ge-N	NF/S,25V,0,3A,0,15W,<300/600ns	2a(B=case)	USA	ASY28..29,ASY73..75
2N1731	Ge-P	NF/S,30V,0,3A,0,15W	2a(B=case)	USA	ASY28,ASY78..77
2N1732	Ge-N	NF/S,30V,0,3A,0,15W	2a(B=case)	USA	ASY28,ASY73..75
2N174(A)	Ge-P	NF/S-L,80V,15A,150W	38a	Del,Mot,++	2N1982,2N2075,2N2079,2N2492..93
2N1742	Ge-P	VHF,20V,0,05A,0,06W	2a	USA,Mot	AF139,AF239(S)
2N1743	Ge-P	VHF,20V,0,05A,0,06W	2a	USA,Mot	AF139,AF239(S)
2N1744	Ge-P	VHF,20V,0,05A,0,06W	2a	USA,Mot	AF139,AF239(S)
2N1745	Ge-P	HF,20V,0,05A,0,08W	2a	USA	AF106,AF109R,AF306
2N1746	Ge-P	HF,20V,0,05A,0,06W	2a	USA	AF108,AF109R,AF306
2N1747	Ge-P	HF,20V,0,05A,0,06W	2a	USA	AF106,AF109R,AF306
2N1748(A)	Ge-P	HF,25V,0,05A,0,06W	2a	USA	AF106,AF109R,AF306
2N1749	Ge-P	HF,40V,0,01A,0,075W	2a	USA	AF106,AF109R,AF306
2N175	Ge-P	HF,10V,2mA,0,02W	1a	USA	AF124..127,AF200
2N1750	Ge-P	HF,14V,5mA,0,015W	37d	Cbs,Phc	AF124..128,AF200
2N1751	Ge-P	S-L,80V,25A,106W	23a	USA,Mot	2N1652..53,2N2286..87
2N1752	Ge-P	HF,12V,0,05A,0,06W	2a	Etc,Spr	AF124..128,AF200
2N1753	Ge-P	HF,30V,0,05A,0,03W	2a	Cen,Phc	AF124..126,AF200
2N1754	Ge-P	HF,13V,0,1A,0,05W	2a	Etc,Spr	(ASY26..27,ASY78..77)
2N1755	Ge-P	S-L,40V,3A,28W,B>30		Gpd,Stc	(AL102..103,AUY19..20,2N1529..48,++)
2N1756	Ge-P	=2N1755:60V		Gpd,Stc	(AL102..103,AUY19..20,2N1545..48,++)
2N1757	Ge-P	=2N1755:80V		Gpd,Stc	(AL102..103,AUY20,2N1548..48,++)
2N1756	Ge-P	=2N1755:100V		Gpd,Stc	(AL102..103,AUY34,2N1547..48,++)
2N1759	Ge-P	S-L,40V,3A,28W,B>80		Gpd,Stc	(AL102..103,AUY19..20,2N1529..48,++)
2N176	Ge-P	NF/S-L,40V,3A,90W	23a	Mot,Stc,++	AD149,AUY19..20,2N2143..48,++
2N1780	Ge-P	=2N1759:80V		Gpd,Stc	(AL102..103,AUY19..20,2N1545..48,++)
2N1761	Ge-P	=2N1759:80V		Gpd,Stc	(AL102..103,AUY20,2N1546..48,++)
2N1762	Ge-P	=2N1759:100V		Gpd,Stc	(AL102..103,AUY34,2N1547..48,++)
2N1783	Si-N	S,40V,0,06A0,3W,<32/56	2a	Ray	2N3722..25,2SC1385
2N1784	Si-N	=2N1763:20V	2a	Ray	2N3722..25,2SC1+F11162385
2N1765	50Hz-Thy	400V,0,5A,Igt/Ih<10/<5mA	2a	Wes	2N1589,BTX30/400,T1N400,TAG1-400++
2N1768	Si-N	S-L,80V,3A,40W		USA	(BD241A,BD535,BD539A,BD935,++)
2N1769	Si-N	=2N1768:100V		USA	(BD241C,BD539C,BD937,2SD712,++)
2N1779	Ge-N	NF/S,25V,0,1A,0,1W,5MHz,B>20	2a	Etc,Syl	ASY26..29,ASY73..75
2N178	Ge-P	NF/S-L,30V,3A,40W	23a	Mot,Stc,++	AD149,AUY19..20,2N2137..46,++
2N1780	Ge-N	=2N1779:8MHz,B>30	2a	Etc,Syl	ASY28..29,ASY73..75
2N1781	Ge-N	=2N1779:6MHz,B>40	2a	Etc,Syl	ASY28..29,ASY73..75
2N1782	Ge-P	NF/S,30V,0,1A,0,1W,8MHz,B>30	2a	Etc,Syl	ASY26,ASY76..77
2N1783	Ge-N	=2N1779:30V,8MHz	2a	Etc,Syl	ASY28,ASY73..75
2N1784	Ge-P	=2N1782:12MHz,B>20	2a	Etc,Syl	ASY26,ASY78..77
2N1765	Ge-P	HF,10V,0,05A,0,045W,≈50MHz	2a	USA	AF124..126,AF200
2N1768	Ge-P	HF,10V,0,05A,0,045W,≈50MHz	2a	USA	AF124..126,AF200
2N1787	Ge-P	HF,15V,0,05A,0,045W,≈50MHz	2a	USA	AF124..126,AF200
2N1768	Ge-P	HF,35V,0,05A,0,06W,≈100MHz	2a	USA	AF106,AF109R,AF306
2N1789	Ge-P	HF,35V,0,05A,0,06W,≈100MHz	2a	USA	AF106,AF109R,AF306
2N179	Ge-P	NF/S-L,-/40V,1A,10W(Tc=75°)	23a	Mot	AD149,AUY19..20,2N2144..48,++
2N1790	Ge-P	HF,35V,0,05A,0,06W,≈100MHz	2a	USA	AF106,AF109R,AF306
2N180	Ge-P	NF/S,30V,0,15W	1a	Csr,Etc	ASY26,ASY76..77
2N1808	Ge-N	NF/S,25V,0,3A,0,15W,14MHz	2a	USA,Tix	ASY28..29,ASY73..75
2N1809	Si-N	S-L,50V,10A,250W	53b	Sem,Whs	—
2N181	Ge-P	=2N180:	2a*	Csr,Etc	ASY26,ASY76..77
2N1810	Si-N	=2N1809:100V	53b	Sem,Whs	—
2N1811	Si-N	=2N1809:150V	53b	Sem,Whs	—
2N1812	Si-N	=2N1809:200V	53b	Sem,Whs	—
2N1813	Si-N	=2N1809:250V	53b	Sem,Whs	—

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2N1814	Si-N	=2N1809: 300V	53b	Sem,Whs	—
2N1815	Si-N	=2N1809: 350V	53b	Sem,Whs	—
2N1816	Si-N	S-L, 50V, 15A, 250W	53b	Sem,Whs	—
2N1817	Si-N	=2N1716: 100V	53b	Sem,Whs	—
2N1818	Si-N	=2N1716: 150V	53b	Sem,Whs	—
2N1819	Si-N	=2N1716: 200V	53b	Sem,Whs	—
2N182	Ge-N	S, 25V, 0,1W, 3,8MHz	1a	Csr,Etc	ASY28..29, ASY73..75
2N1820	Si-N	=2N1716: 250V	53b	Sem,Whs	—
2N1821	Si-N	=2N1716: 300V	53b	Sem,Whs	—
2N1822	Si-N	=2N1716: 350V	53b	Sem,Whs	—
2N1823	Si-N	S-L, 50V, 20A, 250W	53b	Sem,Whs	—
2N1824	Si-N	=2N1823: 100V	53b	Sem,Whs	—
2N1825	Si-N	=2N1823: 150V	53b	Sem,Whs	—
2N1826	Si-N	=2N1823: 200V	53b	Sem,Whs	—
2N1827	Si-N	=2N1823: 250V	53b	Sem,Whs	—
2N1828	Si-N	=2N1823: 300V	53b	Sem,Whs	—
2N1829	Si-N	=2N1823: 350V	53b	Sem,Whs	—
2N183	Ge-N	S, 25V, 0,1W, 7,5MHz	1a	Csr,Etc	ASY26..29, ASY73..75
2N1830	Si-N	S-L, 50V, 25A, 250W	53b	Sem,Whs	—
2N1831	Si-N	=2N1830: 100V	53b	Sem,Whs	—
2N1832	Si-N	=2N1830: 150V	53b	Sem,Whs	—
2N1833	Si-N	=2N1830: 200V	53b	Sem,Whs	—
2N1834	Si-N	=2N1830: 250V	53b	Sem,Whs	—
2N1835	Si-N	=2N1830: 300V	53b	Sem,Whs	—
2N1836	Si-N	=2N1830: 350V	53b	Sem,Whs	—
2N1837(A, B)	Si-N	NF/S, 80V, 0,5A 0,6W, <200/500ns	2a	USA	BC140..141, BC300..301, 2N2218..19A, ++
2N1836	Si-N	NF/S, 45V, 0,5A, 0,6W, <200/800ns	2a	USA	BC140..141, BC300..301, 2N2218..19, ++
2N1839(A)	Si-N	NF/S, 45V, 0,5A, 0,6W, <200/600ns	2a	USA	BC140..141, BC300..301, 2N2218..19, ++
2N184	Ge-N	S, 25V, 0,1W, 15MHz	1a	Csr,Etc	ASY26..29, ASY73..75
2N1840	Si-N	NF/S, 25V, 0,5A, 0,6W, <500/1200ns	2a	USA	BC140..141, BC300..301, 2N2218..19, ++
2N1841	Si-N	NF/S-L, -/50V, 13W, 78MHz	≈2a	Nsc	(BD139, BD230, BD379, 2SC1398, ++)
2N1842	50Hz-Thy	25V, 10A(Tc=80°), Igt/Ih<80/40mA	21b	USA, Tag, Tho	BTW39/50, BTW45/200R, TAG9N400, ++
2N1843	50Hz-Thy	=2N1843: 50V	21b		BTW39/50, BTW45/200R, TAG9N400, ++
2N1844	50Hz-Thy	=2N1643: 100V	21b		BTW39/100, BTW45/200R, TAG9N400, ++
2N1845	50Hz-Thy	=2N1843: 150V	21b		BTW39/200, BTW45/200R, TAG9N400, ++
2N1848	50Hz-Thy	=2N1843: 200V	21b		BTW39/200, BTW45/200R, TAG9N400, ++
2N1847	50Hz-Thy	=2N1843: 250V	21b		BTW39/300, BTW45/300R, TAG9N400, ++
2N1848	50Hz-Thy	=2N1843: 300V	21b		BTW39/300, BTW45/300R, TAG9N400, ++
2N1849	50Hz-Thy	=2N1843: 400V	21b		BTW39/400, BTW45/400R, TAG9N400, ++
2N185	Ge-P	NF/HF, 20V, 0,05A, 0,15W	2a	USA	AC125..126, AC151, ASY26..27
2N1850	50Hz-Thy	=2N1843: 500V	21b		BTW39/500, BTW45/500R, TAG9N600, ++
2N1853(/18)	Ge-P	S, 18V, 0,1A, 0,15W, <800/900ns	2a	USA	(ASY26..27, ASY76..77)
2N1854	Ge-P	S, 18V, 0,1A, 0,15W, >40MHz	2a	USA	(ASY26..27, ASY76..77)
2N186(A)	Ge-P	NF/HF, 25V, 0,2A, 0,1W, B=24	1a	USA	AC125..126, AC151..152
2N1864	Ge-P	HF, 20V, 0,05A, 0,06W, ≈50MHz	2a	USA	AF124..126, AF200
2N1865	Ge-P	HF, 20V, 0,05A, 0,06W, ≈180MHz	2a	USA	AF106, AF109R, AF306
2N1866	Ge-P	HF, 35V, 0,05A, 0,06W, ≈180MHz	2a	USA	AF106, AF109R, AF306
2N1867	Ge-P	HF, 35V, 0,05A, 0,06W, ≈180MHz	2a	USA	AF106, AF109R, AF306
2N1886	Ge-P	HF, 35V, 0,05A, 0,06W, ≈400MHz	2a	USA	AF139, AF239(S)
2N1869(A)	50Hz-Thy	15V, 1,25A(Tc=100°), Igt/Ih<0,2/<5mA	2a	USA, Mot	2N2322, 2N6332, TAG615-100, (MCR606-2)
2N187(A)	Ge-P	=2N186: B=36	1a	USA	AC125..126, AC151..152
2N1870(A)	50Hz-Thy	=2N1869: 30V	2a		2N2323, 2N6333, TAG615-100, (MCR606-2)
2N1871(A)	50Hz-Thy	=2N1869: 80V	2a		2N2324, 2N6334, TAG615-100, (MCR606-3)
2N1872(A)	50Hz-Thy	=2N1869: 100V	2a		2N2324, 2N6334, TAG615-100, (MCR606-3)
2N1873(A)	50Hz-Thy	=2N1869: 150V	2a		2N2325, 2N6335, TAG815-200, (MCR606-4)
2N1874(A)	50Hz-Thy	=2N1869: 200V	2a		2N2326, 2N6336, TAG815-200, (MCR606-4)
2N1875(A)	50Hz-Thy	=2N1869: Igt/Ih<0,02/<3mA	2a	USA, Mot	2N2322A
2N1876(A)	50Hz-Thy	=2N1870: Igt/Ih<0,02/<3mA	2a		2N2323A
2N1877(A)	50Hz-Thy	=2N1871: Igt/Ih<0,02/<3mA	2a		2N2324A
2N1878(A)	50Hz-Thy	=2N1872: Igt/Ih<0,02/<3mA	2a		2N2324A
2N1879(A)	50Hz-Thy	=2N1873: Igt/Ih<0,02/<3mA	2a		2N2325A
2N186(A)	Ge-P	=2N186: B=54	1a	USA	AC125..126, AC151..152
2N1860(A)	50Hz-Thy	=2N1874: Igt/Ih<0,02/<3mA	2a		2N2326A
2N1881	50Hz-Thy	30V, 1A(Tc=100°), Igt/Ih<2,5/<10mA	2a	USA, Mot	TAG2-50, MCR1906-2, TAG614-100
2N1882	50Hz-Thy	=2N1861: 60V	2a		TAG2-100, MCR1906-3, TAG814-100
2N1883	50Hz-Thy	=2N1881: 100V	2a		TAG2-100, MCR1906-3, TAG614-100

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2N1884	50Hz-Thy	=2N1881: 150V	2a		TAG2-200, MCR1906-4, TAG814-200
2N1885	50Hz-Thy	=2N1881: 200V	2a		TAG2-200, MCR1906-4, TAG814-200
2N1888	Si-N	S-L, 60V, 3A, 40W	21	USA	(BD241A, BD535, BD539A, BD935,++)
2N1889	Si-N	NF/S, 100V, 0,5A, 0,8W, >50MHz, B>40	2a	USA,EUR	BC141, BC300, 2N1893(A), 2N1990, ++
2N189	Ge-P	NF/HF, 25V, 0,2A, 0,2W, β=32	1a	USA	AC125..126, AC151..152
2N1890(S)	Si-N	=2N1889: >60MHz, B>100	2a	USA,EUR	BC141, BC300, 2N1893(A), 2N1990, ++
2N1891	Ge-N	NF/S, 25V, 0,3A, 0,15W, >5MHz	2a	USA,Tix	ASY26..29, ASY73..75
2N1892	Ge-P	NF/S, 30V, 0,3A, 0,15W, >5MHz	2a	USA,Tix	ASY26..27, ASY76..77
2N1893(L,S)	Si-N	NF/S, 120V, 0,5A, 0,8W, 70MHz	2a	USA,EUR	BC300, BSY55..56, 2N2102, 2N2405,++
2N1893A	Si-N	=2N1893: 140V, >100MHz	2a		BSS43, BSW68, 2N3019..20
2N1894	Si-N	NF/S-L, 60V, 2A, 85W	49m	Ray	—
2N1895	Si-N	=2N1894: 80V	49m	Ray	—
2N1896	Si-N	NF/S-L, 60V, 2A, 85W	49m	Ray	—
2N1897	Si-N	=2N1896: 80V	49m	Ray	—
2N1898	Si-N	=2N1896: 100V	49m	Ray	—
2N1899	Si-N	NF/S-L, 140V, 10A(ss), 125W, B>10		USA	—
2N190	Ge-P	=2N189: β=42	1a	USA	AC125..126, AC151..152
2N1900	Si-N	=2N1899: B>8		USA	—
2N1901	Si-N	=2N1899: B>20		USA	—
2N1902	Si-N	=2N1899:	49a	USA	—
2N1903	Si-N	=2N1899: B>8	49a	USA	—
2N1904	Si-N	=2N1899: B>20	49a	USA	—
2N1905	Ge-P	S-L, 100V, 6A, 30W(Tc=55°)	23a	USA,Rca,Sgs	AL102..103, AU108, 2N5324..25
2N1906	Ge-P	=2N1905: 130V	23a	USA,Rca,Sgs	AL102, AU110, AU210, 2N5324..25
2N1907(A)	Ge-P	S-L, 100V, 20A, 60W(Tc=70°)	23a	USA,Tix	2N1652..53, 2N2286..87
2N1908(A)	Ge-P	=2N1907: 130V	23a	USA,Tix	2N1653, 2N2287
2N191	Ge-P	=2N189: β=67	1a	USA	AC125..126, AC151..152
2N1917	Si-P	Chopper, 25/8/25V, 0,05A, 0,25W	2a	USA	—
2N1918	Si-P	Chopper, 25/8/25V, 0,05A, 0,25W	2a	USA	—
2N1919	Si-P	Chopper, 40/18/40V, 0,05A, 0,25W	2a	USA	—
2N192	Ge-P	=2N189: β=90	1a	USA	AC125..126, AC151..152
2N1920	Si-P	Chopper, 40/18/40V, 0,05A, 0,25W	2a	USA	—
2N1921	Si-P	Chopper, 50/50/50V, 0,05A, 0,25W	2a	USA	—
2N1922	Si-P	Chopper, 80/80/80V, 0,05A, 0,25W	2a	USA	—
2N1923	Si-N	Uni, 85V, 0,06A, 0,75W, 90MHz	2a	Tix,Sty	BC141, BC300..301, BC546, 2N1889..90,++
2N1924	Ge-P	NF/S, 60V, 0,5A, 0,225W, 1,5MHz, B>34	2a(B=case)	USA,Mot,Tix	ASY77
2N1925	Ge-P	=2N1924: 2,5MHz, B>53	2a(B=case)	USA,Mot,Tix	ASY77
2N1926	Ge-P	=2N1924: 3MHz, B>72	2a(B=case)	USA,Mot,Tix	ASY77
2N193	Ge-N	HF, 18V, 0,25A, 0,15W, 3MHz	2a	USA	ASY26..29, ASY73..75
2N1936	Si-N	NF/S-L, 125/60V, 20A(ss), 200W	49m	USA,Thi,Tix	2N2817..18, 2N2821..F1124122, 2N5539
2N1937	Si-N	=2N1936: 125/80V	49m	USA,Tho,Tix	2N2817..18, 2N2821..22, 2N5539
2N194(A)	Ge-N	HF, 16V, 0,2A, 0,05W, 3MHz	2a	USA	ASY26..29, ASY73..75
2N1940	Ge-P	HF-L, 30V, 0,25A, 3,5W, >350MHz	49a	Mot,Sty	—
2N1941	Si-N	NF-Tr, 45V, 1A, 0,6W, >60MHz	2a	Sty	BC140..141, 2N1990, 2N2102, 2N2405,++
2N1942	Ge-P	NF/S, 20V, 0,5A, 0,2W, >5MHz	2a	USA	ASY76..77
2N1943	Si-N	NF, 60V, 0,5A, 0,8W	2a	USA	BC140..141, BC300..302, 2N3053,++
2N1944	Si-N	NF/S, 20V, 1A, 0,6W, >60MHz, B>150	2a	USA	BC140..141, 2N1990, 2N2101, 2N2405,++
2N1945	Si-N	=2N1944: 30V	2a	USA	BC140..141, 2N1990, 2N2101, 2N2405,++
2N1946	Si-N	=2N1944: 40V	2a	USA	BC140..141, 2N1990, 2N2101, 2N2405,++
2N1947	Si-N	NF/S, 20V, 1A, 0,6W, >60MHz, B>500	2a	USA	(BC140..141, 2N1990, 2N2101, 2N2405,++)
2N1948	Si-N	=2N1947: 30V	2a	USA	(BC140..141, 2N1990, 2N2101, 2N2405,++)
2N1949	Si-N	=2N1947: 40V	2a	USA	(BC140..141, 2N1990, 2N2101, 2N2405,++)
2N195	Ge-P	Uni, 15V, 0,03A, 0,1W	2a	Tra	AC125..126, AC151
2N1950	Si-N	NF/S, 20V, 1A, 0,6W, >60MHz, B>250	2a	USA	(BC140..141, 2N1990, 2N2101, 2N2405,++)
2N1951	Si-N	=2N1950: 30V	2a	USA	(BC140..141, 2N1990, 2N2101, 2N2405,++)
2N1952	Si-N	=2N1950: 40V	2a	USA	(BC140..141, 2N1990, 2N2101, 2N2405,++)
2N1953	Si-N	NF/S, 20V, 1A, 0,6W, >40MHz	2a	USA	BC140..141, 2N1990, 2N2101, 2N2405,++
2N1954	Ge-P	NF/S, 60/20V, 0,2A, 0,2W	2a	USA	ASY77
2N1955	Ge-P	NF/S, 60/18V, 0,2A, 0,2W	2a	USA	ASY77
2N1956	Ge-P	NF/S, 60/16V, 0,2A, 0,2W	2a	USA	ASY77
2N1957	Ge-P	NF/S, 60/14V, 0,2A, 0,2W	2a	USA	ASY77
2N1958	Si-N	S, 60V, 0,5A, 0,6W, <85/45ns, B>20	2a	USA	BSS27, BSV77, BSV95, 2N5189, ++
2N1958A	Si-N	=2N1958: 1A, <80/45ns	2a		BSS27, BSV77, BSV95, 2N5189, ++
2N1959	Si-N	S, 60V, 0,5A, 0,6W, <85/45ns, B>40	2a	USA	BSS27, BSV77, BSV95, 2N5189, ++
2N1959A	Si-N	=2N1959: 1A, <60/45ns	2a		BSS27, BSV77, BSV95, 2N5189, ++
2N196	Ge-P	Uni, 30V, 0,03A, 0,1W	2a	Tra	AC125..126, AC151

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2N1960(/46)	Ge-P	S, 15V, 0,2A, 0,15W, <60/70ns	2a	Nsc,Syl	2N964(A), 2N2635, 2N2955..57
2N1961(/46)	Ge-P	S, 12V, 0,2A, 0,15W, <75/110ns	2a	Nsc,Syl	2N960..2N967, 2N2635, 2N2955..57
2N1962(/46)	Si-N	Uni, 40V, 0,2A, 0,4W, <18/30ns	2a	Syl	BSS10..11, BSX19..20, 2N2366..69(A),++
2N1963(/46)	Si-N	Uni, 30V, 0,2A, 0,4W, <20/40ns	2a	Syl	BSS10..11, BSX19..20, 2N2368..69(A),++
2N1964(/46)	Si-N	Uni, 60V, 0,5A, 0,4W, <65/45ns	2a	Syl	2N4014
2N1965(/46)	Si-N	Uni, 60V, 0,5A, 0,4W, <65/45ns	2a	Syl	2N4014
2N1966..1968	Opto				—
2N1969	Ge-P	NF/S, 30V, 0,4A, 0,15W, >10MHz	2a	USA	ASY76..77
2N197	Ge-P	Uni, 30V, 0,03A, 0,1W	2a	Tra	AC125..126, AC151
2N1970	Ge-P	NF/S-L, 100V, 15A, 170W	36a	USA, Mot	2N2493
2N1971	Ge-P	NF/S-L, 60V, 4A, 38W	23a	USA	AL102..103, AUY26, 2N1546..46,++
2N1972	Si-N	Uni, 60V, 1A, 0,8W, >50MHz	2a	USA,Fch	BC140..141, 2N1990, 2N2102, 2N2405,++
2N1973	Si-N	NF/S, 100V, 0,8W, >60MHz, B>75	2a	USA,Fch,Tix	BC141, BC300, 2N1689..90, 2N1990,++
2N1974	Si-N	NF/S, 100V, 0,6W, >50MHz, B>35	2a	USA,Fch,Tix	BC141, BC300, 2N1889..90, 2N1990,++
2N1975	Si-N	NF/S, 100V, 0,6W, >40MHz, B>15	2a	USA,Fch,Tix	BC141, BC300, 2N1889..90, 2N1990,++
2N1976	Si-N	NF/S-L, 60V, 30W(Tc=100°), >40MHz	≈37a	Fch,Sgs	—
2N196	Ge-P	Uni, 30V, 0,03A, 0,1W	2a	Tra	AC125..126, AC151
2N1960	Ge-P	NF/S-L, 50V, 15A, 170W	38a	USA, Mot	2N2075..77, 2N2079..81, 2N2490..93
2N1981	Ge-P	NF/S-L, 70V, 15A, 170W	38a	USA, Mot	2N2075..76, 2N2079..80, 2N2492..93
2N1982	Ge-P	NF/S-L, 90V, 15A, 170W	38a	USA, Mot	2N2493
2N1963	Si-N	Uni, 50V, 1A, 0,6W, >40MHz, β>60	2a	USA,Mot,Sgs	BC140..141, 2N1990, 2N2102, 2N2405,++
2N1964	Si-N	=2N1983: β>40	2a	USA,Mot,Sgs	BC140..141, 2N1990, 2N2102, 2N2405,++
2N1965	Si-N	=2N1963: β>20	2a	USA,Sgs	BC140..141, 2N1990, 2N2102, 2N2405,++
2N1986	Si-N	Uni, 50V, 1A, 0,6W, >40MHz, B>60	2a	USA,Sgs	BC140..141, 2N1990, 2N2102, 2N2405,++
2N1967	Si-N	=2N1966: B>20	2a	USA,Sgs	BC140..141, 2N1990, 2N2102, 2N2405,++
2N1996	Si-N	Uni, 100V, 1A, 0,6W, >40MHz, B>35	2a	USA,Sgs	BC141, 2N1990, 2N2102, 2N2405,++
2N1989	Si-N	=2N1966: B>20	2a	USA,Sgs	BC141, 2N1990, 2N2102, 2N2405,++
2N199	Ge-P	Uni, 30V, 0,03A, 0,1W	2a	Tra	AC125..126, AC151
2N1990(N,R,W)	Si-N	=2N1990(S): 0,25..0,3W	2a		BC639, 2N3700..01, 23D667, 2SD774,++
2N1990(S)	Si-N	Nix, 100V 1A, 0,6W	2a	USA,EUR,Mic	BC141, 2N1990, 2N2102, 2N2405,++
2N1991(S)	Si-P	NF/S, 30V, 0,6A, 0,6W, >40MHz	2a	USA,Mot,3gs	BC160..161, BC303..304, 2N2303,++
2N1992	Si-N	S, -/15V, 0,05A, 0,35W, 430MHz	2a	Nsc	BSV89..92, BSX92..93, 2N2368..69(A),++
2N1993	Ge-N	NF/S, 30/18/30V, 0,3A, 0,15W, >3MHz	2a	USA,Tix	(ASY26, ASY73..75)
2N1994	Ge-N	S, bidirektional, 30V, 0,3A, 0,15W	2a(B=case)	USA,Tix	—
2N1995	Ge-N	=2N1994: 25V	2a(B=case)	USA,Tix	—
2N1996	Ge-N	=2N1994: 20V	2a(B=case)	USA,Tix	—
2N1997	Ge-P	NF/S, 45V, 0,5A, 0,25W, >3MHz	2a	USA,Tix	ASY77
2N1998	Ge-P	=2N1997: 35V	2a	USA,Tix	ASY76..77
2N1999	Ge-P	=2N1997: 30V	2a	USA,Tix	ASY76..77
2N200	Ge-P	Uni, 36V, 0,1A, 0,1W	2a	Tra	AC125..126, AC151
2N2000	Ge-P	S, 50V, 1A, 0,3A, >2MHz	2a(B=case)	USA,Tix	—
2N2001	Ge-P	=2N2000: 30V	2a(B=case)	USA,Tix	—
2N2002	Si-P	Chopper, 30/5/30V, 0,1A 0,25W	2a	USA	2N2946
2N2003	Si-P	Chopper, 30/5/30V, 0,1A, 0,25W	2a	USA	2N2946
2N2004	Si-P	Chopper, 50/15/50V, 0,1A, 0,25W	2a	USA	2N2946
2N2005	Si-P	Chopper, 50/15/50V, 0,1A, 0,25W	2a	USA	2N2946
2N2006	Si-P	Chopper, 60/35/60V, 0,1A, 0,25W	2a	USA	—
2N2007	Si-P	Chopper, 60/35/60V, 0,1A, 0,25W	2a	USA	—
2N2008	Si-N	Uni, 175V, 0,5A, 0,6W, >40MHz	2a	USAFch	BSS46..49, 2N3439..40
2N2009	50Hz-Thy	25V, 1,3A(Tc=60°C), Igt/Ih<0,2/<5mA	2a	USA,Mot, Tag	2N2322, 2N6332, TAG615-100, (MCR606-2)
2N2010	50Hz-Thy	=2N2009: 50V	2a		2N2323, 2N6333, TAG615-100, (MCR606-2)
2N2011	50Hz-Thy	=2N2009: 100V	2a		2N2324, 2N6334, TAG615-100, (MCR606-3)
2N2012	50Hz-Thy	=2N2009: 200V	2a		2N2326, 2N6335, TAG615-200, (MCR606-4)
2N2013	50Hz-Thy	=2N2009: 300V	2a		2N2326+F11303, 2N6336, TAG615-300, (MCR606-5)
2N2014	50Hz-Thy	=2N2009: 400V	2a		2N2329, 2N6337, TAG615-400, (MCR606-6)
2N2015	Si-N	S-L, 100V, 10A, 150W	38a	Ssi,Stc	—
2N2016	Si-N	=2N2015: 130V	38a	Ssi,Stc	—
2N2017	Si-N	Uni, 60V, 1A, 1W	2a	USA,Nsc	BC140..141, 2N1990, 2N2102, 2N2405,++
2N2018	Si-N	S-L, 150V, 2A, 40W, 10MHz	≈21	USA	—
2N2019	Si-N	S-L, 200V, 2A, 40W, 10MHz	≈21	USA	—
2N2020	Si-N	S-L, 150V, 2A, 40W, 10MHz	≈21	USA	—
2N2021	Si-N	S-L, 200V, 2A, 40W, 10MHz	≈21	USA	—
2N2022	Ge-P	S, 15V, 0,05A, >250MHz, <60/-ns	2a	Wes	(ASZ21, 2N705, 2N964(A))
2N2032	Si-N	S-L, 45V, 5A, 65W		USA,Tix	(BD245, BD543, BD545A, BDV91,++)
2N2033	Si-N	S-L, 60V, 3A, 5W(Tc=25°)	2a	USA	BSX64, BUY41, 2N4236..39, 2SC2214
2N2033S	Si-N	=2N2033: 6,5W	49m		(BD179, BD241B, BD441, BD619,++)

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2N2034	Si-N	S-L, 80V, 3A, 5W(Tc=25°)	2a	USA	BSX64, BUY41, 2N4238..39, 2SC2214
2N2034S	Si-N	=2N2034: 8,5W	49m		(BD179, BD241B, BD441, BD619,++)
2N2035	Si-N	S-L, 80V, 3A, 14W(Tc=25°)	2a	USA	(BD179, BD241B, BD441, BD619,++)
2N2036	Si-N	S-L, 80V, 3A, 10W(Tc=25°)	43m	USA	(BD179, BD241B, BD441, BD619,++)
2N2039	Si-N	NF-Tr, 45V, 0,5A, 0,6W(Ta=100°), B>12	2a	USA	BC140..141, BC300..302, 2N3053,++
2N2039	Si-N	=2N3039: 75V	2a	USA	BC140..141, BC300..301, 2N1613,++
2N204	Ge-P	Uni, 36V, 0,1A, 0,1W, β>50	2a	Tra	AC125..126, AC151
2N2040	Si-N	NF-Tr, 45V, 0,5A, 0,6W(Ta=100°), B>30	2a	USA	BC140..141, BC300..302, 2N3053,++
2N2041	Si-N	=2N3040: 75V	2a	USA	BC140..141, BC300..301, 2N1613,++
2N2042(A)	Ge-P	NF/S, 105V, 0,2A, 0,2W, B>20	2a	USA, Mot	ACY39, 2N398
2N2043(A)	Ge-P	NF/S, 105V, 0,2A, 0,2W, B>20	2a	USA, Mot	ACY39, 2N398
2N2048	Ge-P	S, 20V, 0,1A, 0,15W, >150MHz	2a	USA	2N2955..57
2N2048A	Ge-P	=2N2048: 30V	2a		2N2955..57
2N2049	Si-N	Uni, 75V, 0,5A, 0,8W, >50MHz	2a	USA, Fch	BC140..141, BC300..302, 2N1711,++
2N205	Ge-P	=2N204: β>15	2a	Tra	AC125..126, AC151
2N2059	Ge-P	S, 10V, 0,05A, 0,06W, <8/25ns	2a	Cen	(ASZ21, 2N705, 2N960..67, 2N2955..57)
2N206	Ge-P	NF, 30V, 0,05A, 0,075W	2a	Etc	AC125..126, AC151
2N2060(A,B)	Si-N	Dual, 100V, 0,5A, 0,6W, >60MHz	TO-77	USA, EUR	BFX70..72, 2N2223
2N2061	Ge-P	S-L, 20V, 3A, 40W	23a	USA, Itt	AL102..103, AUY26, 2N1529..48,++
2N2061A	Ge-P	=2N2061: 5A, 90W	23a		AL102..103, AUY28, 2N1529..48,++
2N2062	Ge-P	S-L, 20V, 3A, 40W	23a	USA, Itt	AL102..103, AUY26, 2N1529..48,++
2N2062A	Ge-P	=2N2062: 5A, 90W	23a		AL102..103, AUY28, 2N1529..48,++
2N2063	Ge-P	S-L, 40V, 3A, 35W	23a	USA, Itt	AL102..103, AUY26, 2N1529..48,++
2N2063A	Ge-P	=2N2063: 5A, 90W	23a		AL102..103, AUY26, 2N1529..48,++
2N2064	Ge-P	S-L, 40V, 3A, 35W	23a	USA, Itt	AL102..103, AUY28, 2N1529..48,++
2NA113412064A	Ge-P	=2N2064: 5A, 90W	23a		AL102..103, AUY28, 2N1529..48,++
2N2065	Ge-P	S-L, 80V, 3A, 35W	23a	USA, Itt	AL102..103, AUY28, 2N1548..48,++
2N2065A	Ge-P	=2N2065: 5A, 90W	23a		AL102..103, AUY28, 2N1546..48,++
2N2066	Ge-P	S-L, 80V, 3A, 35W	23a	USA, Itt	AL102..103, AUY26, 2N1546..48,++
2N2066A	Ge-P	=2N2066: 5A, 90W	23a		AL102..103, AUY28, 2N1546..48,++
2N2067	Ge-P	NF/S-L, 40V, 3A, 28W		USA	—
2N2068	Ge-P	=2N2067: 80V		USA	—
2N2069	Ge-P	NF/S-L, 40V, 12A, 75W	23a	Cen	2N1549..80
2N207(A, B)	Ge-P	NF, 12/12/12V, 0,02A, 0,068W	2a	USA	ASY28..27
2N2070	Ge-P	=2N2069: 80V	23a	Cen	2N1551..52, 2N1555..56, 2N1559..80
2N2071	Ge-P	=2N2069	23a	Cen	2N1549..80
2N2072	Ge-P	=2N2069: 80V	23a	Cen	2N1551..52, 2N1555..56, 2N1559..80
2N2075(A)	Ge-P	S-L, 80V, 15A, 170W, B>20	38a	USA, Mot	2N1982, 2N2492..93
2N2076(A)	Ge-P	=2N2075: 70V	38a	USA, Mot	2N1981..82, 2N2492..93
2N2077(A)	Ge-P	=2N2075: 50V	38a	USA, Mot	2N1980..82, 2N2490..93
2N2078(A)	Ge-P	=2N2075: 40V	38a	USA, Mot	2N1980..82, 2N2490..93
2N2079(A)	Ge-P	S-L, 80V, 15A, 170W, B>35	38a	USA, Mot	2N1982, 2N2492..93
2N2060(A)	Ge-P	=2N2079: 70V	39a	USA, Mot	2N1981..82, 2N2492..93
2N2061(A)	Ge-P	=2N2079: 50V	38a	USA, Mot	2N1980..82, 2N2490..93
2N2062(A)	Ge-P	=2N2079: 40V	38a	USA, Mot	2N1980..82, 2N2490..93
2N2083	Ge-P	HF, 30V, 10mA, 0,06W, >30MHz	1g	Cen, Sty	AF124..126, AF200
2N2064	Ge-P	HF, 40V, 10mA, 0,125W, >100MHz	5g	Spa, Sty	AF106, AF109R, AF306
2N2065	Ge-N	NF/S, 33V, 0,5A, 0,15W, 8MHz	2a	USA	ASY28, ASY73..75
2N2066	Si-N	NF/S, 120V, 0,5A, 0,6W, >150MHz, B>20	2a	USA	BC300, 2N1893(A), 2N2102, 2N2405,++
2N2087	Si-N	=2N2068: B>40	2a	USA	BC300, 2N1893(A), 2N2102, 2N2405,++
2N2089	Ge-P	HF, 20V, 10mA, 0,1W, >44MHz	1g	Amp	AF124..126, AF200
2N2090	Ge-P	HF, 20V, 10mA, 0,1W, >44MHz	1g	Amp	AF124..126, AF200
2N2091	Ge-P	HF, 20V, 10mA, 0,1W, >44MHz	1g	Amp	AF124..126, AF200
2N2092	Ge-P	HF, 20V, 10mA, 0,1W, >30MHz	1g	Amp	AF124..126, AF200
2N2093	Ge-P	HF, 25V, 10mA, 0,1W, >30MHz	1g	Amp	AF124..126, AF200
2N2094	Si-N	Uni, 60/40V, 0,6W, >200MHz	2a	Spr	BFR10, BFX98..97, 2N3722..23, 2SC1385,++
2N2094A	Si-N	=2N2094: 60/60V	2a		BFR10, BFX98..97, 2N3722..23, 2SC1385,++
2N2095	Ge-P	HF-L, 30V, 0,3A, >500MHz	49m	Ssi	—
2N2096	Ge-P	S, 25V, 0,5A, 0,5W, -/130ns	49m	USA, Mot	2N1494
2N2097	Ge-P	S, 40V, 0,5A, 0,5W, -/90ns	49m	USA, Mot	2N1498
2N2098	Ge-P	HF, 30V, 0,3A, 1W, >500MHz	2a	Spr	—
2N2099	Ge-P	=2N2096: 0,3W	2a	USA, Mot	2N1495
2N21(A)	Ge-P	NF/S, 100V, 0,25A, 0,12W	2a	Wes	(ACY39, 2N2042..43)
2N2100(A)	Ge-P	=2N2097: 0,3W	2a	USA, Mot	2N1495
2N2101	Si-N	S-L80V, 3A, 75W	49m	USA	2N3487..92
2N2102(A,L,S)	Si-N	NF/S, 120V, 1A, 1W, >120MHz	2a	USA, EUR	BSS42..43, BSX47, 2N2405, 2N3019..20++

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2N2104	Si-P	NF/S, 50V, 0,6A, 0,6W, 60MHz, B>25	2a	old	BC161, BC303..304, 2N2303, 2SA606, ++
2N2105	Si-P	=2N2104: B>15	2a	old	BC161, BC303..304, 2N2303, 2SA606, ++
2N2106	Si-N	NF/S, 60V, 0,5A, 1W, B>12	2a	USA	BC140..141, BC300..302, 2N3053, ++
2N2107	Si-N	=2N2106: B>30	2a	USA	BC140..141, BC300..302, 2N3053, ++
2N2108	Si-N	=2N2106: B>75	2a		BC140..141, BC300..302, 2N3053, ++
2N2109	Si-N	S-L, 50V, 30A, 250W(Tc=60°)	21b	USA, Whs	2N6324..25
2N211	Ge-N	NF/HF, 18V, 0,25A, 0,05W, 3MHz	2a	Csr, Etc	ASY26..29, ASY73..75
2N2110	Si-N	=2N2109: 100V	21b	USA, Whs	2N6324..25
2N2111	Si-N	=2N2109: 150V	21b	USA, Whs	2N6324..25
2N2112	Si-N	=2N2109: 200V	21b	USA, Whs	2N6324..25
2N2113	Si-N	=2N2109: 250V	21b	USA, Whs	2N6324..25
2N2114	Si-N	=2N2109: 300V	21b	USA, Whs	2N6324..25
2N2115	Si-N	=2N2109: 350V	21b	USA, Whs	2N6324..25
2N2116	Si-N	S-L, 50V, 30A, 250W(Tc=60°)	21b	USA, Whs	2N6324..25
2N2117	Si-N	=2N2116: 100V	21b	USA, Whs	2N6324..25
2N2118	Si-N	=2N2116: 150V	21b	USA, Whs	2N6324..25
2N2119	Si-N	=2N2116: 200V	21b	USA, Whs	2N6324..25
2N212	Ge-N	NF/HF, 18V, 0,25A, 0,15W, >4MHz	2a	Csr, Etc	ASY28..29, ASY73..75
2N2120	Si-N	=2N2116: 250V	21b	USA, Whs	2N6324..25
2N2121	Si-N	=2N2116: 300V	21b	USA, Whs	2N6324..25
2N2122	Si-N	=2N2116: 350V	21b	USA, Whs	2N6324..25
2N2123	Si-N	S-L, 50V, 30A, 250W(Tc=60°)	21b	USA, Whs	2N6324..25
2N2124	Si-N	=2N2123: 100V	21b	USA, Whs	2N6324..25
2N2125	Si-N	=2N2123: 150V	21b	USA, Whs	2N6324..25
2N2126	Si-N	=2N2123: 200V	21b	USA, Whs	2N6324..25
2N2127	Si-N	=2N2123: 250V	21b	USA, Whs	2N6324..25
2N2128	Si-N	=2N2123: 300V	21b	USA, Whs	2N6324..25
2N2129	Si-N	=2N2123: 350V	21b	USA, Whs	2N6324..25
2N213(A)	Ge-N	NF, 18V, 0,25A, 0,05W	2a	Csr, Etc	(AC127)
2N2130	Si-N	S-L, 50V, 30A, 250W(Tc=60°)	21b	USA, Whs	2N6324..25
2N2131	Si-N	=2N2130: 100V	21b	USA, Whs	2N6324..25
2N2132	Si-N	=2N2130: 150V	21b	USA, Whs	2N6324..25
2N2133	Si-N	=2N2130: 200V	21b	USA, Whs	2N6324..25
2N2134	Si-N	=2N2130: 250V	21b	USA, Whs	2N6324..25
2N2135	Si-N	=2N2130: 300V	21b	USA, Whs	2N6324..25
2N2136	Si-N	=2N2130: 350V	21b	USA, Whs	2N6324..25
2N2137(A)	Ge-P	NF/S-L, 30V, 3A, 70W, B>30	23a	USA, Mot	AL102..103, AUY19..20, 2N1529..48, ++
2N2138(A)	Ge-P	=2N2137: 45V	23a	USA, Mot	AL102..103, AUY19..20, 2N1545..48, ++
2N2139(A)	Ge-P	=2N2137: 60V	23a	USA, Mot	AL102..103, AUY19..20, 2N1545..48, ++
2N214(A)	Ge-N	NF, 40V, 0,1A, 0,18W	2a	Csr, Etc	(AC127)
2N2140(A)	Ge-P	=2N2137: 75V	23a	USA, Mot	AL102..103, AUY19..20, 2N1546..46, ++
2N2141(A)	Ge-P	=2N2137: 90V	23a	USA, Mot	AL102..103, AUY28, 2N1547..48, ++
2N2142(A)	Ge-P	NF/S-L, 30V, 3A, 70W, B>50	23a	USA, Mot	AL102..103, AUY19..20, 2N1529..48, ++
2N2143(A)	Ge-P	=2N2142: 45V	23a	USA, Mot	AL102..103, AUY19..20, 2N1545..48, ++
2N2144(A)	Ge-P	=2N2142: 60V	23a	USA, Mot	AL102..103, AUY19..20, 2N1545..48, ++
2N2145(A)	Ge-P	=2N2142: 75V	23a	USA, Mot	AL102..103, AUY19..20, 2N1546..48, ++
2N2146(A)	Ge-P	=2N2142: 90V	23a	USA, Mot	AL102..103, AUY28, 2N1547..46, ++
2N2147	Ge-P	NF-L, 75V, 5A, 12,5W(Tc=81°)	23a	USA, Rca	AL102..103, AUY22, 2N3617..18, ++
2N2148	Ge-P	=2N2147: 60V	23a	USA, Rca	AL102..103, AUY22, 2N3617..18, ++
2N2149	Si-N	100V		Nec	—
2N215	Ge-P	NF, 30V, 0,03A, 0,15W	2a	USA	AC125..126, AC151
2N2150	Si-N	S-L, 125V, 2A, 30W(Tc=100°), B>20	≈49m	USA, Tix	2N5284..85
2N2151	Si-N	=2N2150: B>40	≈49m	USA, Tix	2N5284..8+F114345
2N2152(9A)	Ge-P	NF/S-L, 45V, 30A, 170W, B>50	36a	USA, Mot	—
2N2153(A)	Ge-P	=2N2152: 60V	36a	USA, Mot	—
2N2154(A)	Ge-P	=2N2152: 75V	36a	USA, Mot	—
2N2155(A)	Ge-P	=2N2152: 90V	38a	USA, Mot	—
2N2156(A)	Ge-P	NF/S-L, 45V, 30A, 170W, B>60	38a	USA, Mot	—
2N2157(A)	Ge-P	=2N2156: 60V	38a	USA, Mot	—
2N2158(A)	Ge-P	=2N2156: 75V	38a	USA, Mot	—
2N2159(A)	Ge-P	=2N2156: 90V	38a	USA, Mot	—
2N216	Ge-N	NF/HF, 18V, 0,25A, 0,05W, 3MHz	2a	Csr, Etc	ASY28..29, ASY73..75, (AC127)
2N2160	UJT-P	=2N1671A	5e, 21	Gen, Ssc, Tix	—
2N2161	Si-N	NF/S, 55V, 0,05A, 0,2W, <350/700ns	2a	Gen	BC167, BC182, BC237, BC547, ++
2N2162	Si-P	Chopper, 30/-/30V, 0,15W	2a	USA	2N2946
2N2163	Si-P	Chopper, 15/-/15V, 0,15W	2a	USA	2N2946

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2N2164	Si-P	Chopper, 12/-/12V, 0,15W	2a	USA	2N2946
2N2165	Si-P	Chopper, 30/-/30V, 0,15W	2a	USA	2N2946
2N2166	Si-P	Chopper, 15/-/15V, 0,15W	2a	USA	2N2946
2N2167	Si-P	Chopper, 12/-/12V, 0,15W	2a	USA	2N2946
2N2166	Ge-P	S, 20V, 0,1A, 0,06W, 450MHz	2a	USA	(2N2635, 2N2955..57)
2N2169	Ge-P	S, 15V, 0,1A, 0,06W, 450MHz	2a	USA	(2N705, 2N964(A), 2N2635, 2N2955..57)
2N217	Ge-P	NF, 35V, 0,15A, 0,165W	2a	USA	AC125..126, AC151
2N2170	Ge-P	S, 15V, 0,1A, 0,06W, 350MHz	2a	USA	(2N705, 2N964(A), 2N2635, 2N2955..57)
2N2171	Ge-P	NF/S, 50V, 0,4A, 0,225W, 7,5MHz	2a	USA, Mot	ASY77, 2N1169..90
2N2172	Ge-P	NF/S, 20V, 0,4A, 0,2W, >5MHz	2a	USA	AC126, AC152..153, ASY77, 2N1169..90
2N2173	Ge-P	NF/S, 25V, 0,75A, 0,24W	2a	Spr	AC128, AC153
2N2174	Si-P	NF/S, 45V, 0,4W, 1MHz		Nsc	BC212, BC257, BC307, BC557, ++
2N2175	Si-P	Uni, sym, 6/6/6V, 0,05A, 0,1W, >10MHz	2a	USA	(BC213, BC256, BC308, BC556, ++)
2N2176	Si-P	Uni, sym, 6/6/6V, 0,05A, 0,1W, >10MHz	2a	USA	(BC213, BC256, BC308, BC558, ++)
2N2177	Si-P	Uni, sym, 6/6/6V, 0,05A, 0,1W, >8MHz	2a	USA	(BC213, BC258, BC306, BC558, ++)
2N2176	Si-P	Uni, sym, 6/6/6V, 0,05A, 0,1W, >6MHz	2a	USA	(BC213, BC256, BC308, BC558, ++)
2N218	Ge-P	HF/S, 16V, 15mA, 0,036W, 13MHz	2a	Csr, Etc	AF124..127, AF200
2N2180	Ge-P	HF/S, 15/6/15V, 0,05A, 0,05W, >60MHz	37d	Phc	—
2N2161	Si-P	Chopper, 25/25/25V, 0,05A, 0,15W	2a	Phc, Rsy	2N2946
2N2182	Si-P	=2x2N2161 gep	2a	Phc, Ray	2x2N2946
2N2163	Si-P	Chopper, 15/10/15V, 0,05A, 0,15W	2a	Phc, Ray	2N2946
2N2164	Si-P	=2x2N2183 gep	2a	Phc, Ray	2x2N2946
2N2165	Si-P	Chopper, 30/30/30V, 0,05A, 0,15W	2a	Sem, Tdy	2N2946
2N2166	Si-P	=2x2N2185 gep	2a	Sem, Tdy	2x2N2946
2N2167	Si-P	=2x2N2185 gep	2a	Sem, Tdy	2x2N2946
2N2188	Ge-P	HF, 40V, 0,03A, 0,125W, >60MHz	2a	USA, Tix	AF124..125, AF200
2N2169	Ge-P	=2N2166: >102MHz	2a	USA, Tix	AF106, AF109R, AF308
2N219	Ge-P	RF/IF AMP, 20V, 10mA, 0,08W, 400MHz	4g	Csr, Etc	AF124..127, AF200
2N2190	Ge-P	=2N2166: 80V	2a	USA, Tix	(AF124..125, AF200)
2N2191	Ge-P	=2N2188: 80V, >102MHz	2a	USA, Tix	(AF106, AF109R, AF308)
2N2192(A,B)	Si-N	NF/S, 80V, 1A, 0,6W, >50MHz	2a	USA, EUR	BC140..141, BSW27..28, 2N3252..53, ++
2N2193(A,AS,B)	Si-N	NF/S, 80V, 1A, 0,6W, >50MHz	2a	USA, EUR	BC140..141, BSW39, 2N3444
2N2194(A,B)	Si-N	NF/S, 80V, 1A, 0,8W, >50MHz	2a	USA, EUR	BC140..141, BSW27..26, 2N3252..53, ++
2N2195(A,B)	Si-N	NF/S, 45V, 1A, 0,6W, >50MHz	2a	USA, EUR	BC140..141, BSW27..26, 2N3252..53, ++
2N2196	Si-N	NF/S-L, 80V, 1A, 15W, B>30	43m	USA, Tho	(BD139, BD230, BD387, BD829, ++)
2N2197	Si-N	=2N2196: B>75	43m	USA, Tho	(BD139, BD230, BD387, BD829, ++)
2N2196	Si-N	NF, 80V, 0,2A, 0,8W, >4MHz	2a	Cen, Etc	BC140..141, BC300..302, 2N3053, ++
2N2199	Ge-P	HF, 15V, 0,1A, 0,075W, >120MHz	2a	USA	AFY16, 2N3323..25
2N22	Ge-P	NF/S, 100V, 0,02A, 0,12W		Wes	(ACY39, 2N2042..43)
2N220	Ge-P	NF, 10V, 2mA, 0,02W	2a	Csr, Etc	(AC125..126, AC151)
2N2200	Ge-P	HF, 15V, 0,1A, 0,075W, >120MHz	2a	USA	AFY16, 2N3323..25
2N2201	Si-N	NF/S, 120V, 1A, >10MHz	43m	USA	(BD524, 2SC2690, 2SC3421, 2SD1381..62)
2N2202	Si-N	=2N2201:	2a	USA	(BD524, 2SC2690, 2SC3421, 2SD1381..62)
2N2203	6i-N	=2N2201:	5g	USA	(BD524, 29C2690, 2SC3421, 2SD1381..82)
2N2204	Si-N	=2N2201:		USA	(BD524, 2SC2690, 2SC3421, 2SD1381..82)
2N2205	Si-N	S, 25V, 0,2A, 0,3W, 35/60ns, B>20	2a	USA, Sgs	BSS11..12, BSX19..20, 2N2368..69(A), ++
2N2206	Si-N	=2N2205: B>40	2a	USA, Mot	BSS11..12, BSX19..20, 2N2368..69(A), ++
2N2207	Ge-P	HF, 70V, 0,05A, 0,26W, >140MHz	1g	USA, Phi	(AF118)
2N2208	Ge-P	HF, 30V, 10mA, 0,12W	4e	USA	AF124..126, AF200
2N2209	Ge-P	NF/S, 30V, 0,1A, 0,15W, >8MHz	2a	Cen, Stc	ASY26, ASY76..77
2N2210	Ge-P	NF/S-L, 100V, 15A, 70W	38a	USA	2N2493
2N2211	Ge-P	NF/S-L, 80V, 5A, 90W	23a	Cen, Sty	AL102..103, AUY29, 2N1546..48, ++
2N2212	Ge-P	S-L, 120V, 10A, 102W	23a	USA, Mot	AL100, AUY38, 2N2290, 2N2293, 2N2527
2N2213	UJT-P	40V, 0,45W, Rbb<9,1kΩ		Gen	—
2N2214	Si-N	S, 25V, 0,2A, 0,25W, 200MHz	24b	Trw	BC238, BC548, BSW41, 2N706A, 2N708, ++
2N2216	Si-P	NF/S, 150V, 0,25A, 0,6W, 40MHz	2a	old	2N3636..37, 2N5415, 2SA712
2N2217	Si-N	Uni, 60V, 0,8A, 0,6W, >250MHz, B>20	2a	USA, Mic, Tix	BSW51..54, BSX59..61, 2N3444, ++
2N2217A	Si-N	=2N2217: 75V	2a		BSW51..54, BSX59..61, 2N3444, ++
2N2216(A)	Si-N	=2N2217: B>40	2a	USA, EUR, Mic	BSW51..54, BSX59..61, 2N3444, ++
2N2219(A)	Si-N	=2N2217: B>100	2a	USA, EUR, Mic	BSW51..54, BSX59..61, 2N3444, ++
2N222	Ge-P	Uni, 12V, 0,07W		Gie	—
2N2220(A)	Si-N	=2N2217: 0,5W	2a	USA, Mic, Tix	BSS40..41, BSW61..64, 2N4014, ++
2N2221(A)	Si-N	=2N2217: 0,5W, B>40	2a	USA, EUR, Mic	BSS40..41, BSW61..64, 2N4014, ++
2N2222(A)	Si-N	=2N2217: 0,5W, B>100	2a	USA, EUR, Mic	BSS40..41, BSW61..64, 2N4014, ++
2N2223	Si-N	Dual, 100V, 0,5A, 0,6W, >50MHz	TO-77	USA, Fer, Gen	BFX70..72, 2N2060
2N2223	Si-N			Mot, Sgs, Tix	—

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2N2224	Si-N	S, 65V, 0,5A, 0,8W, >250MHz	2a	USA, Mot	BC 140..141, BC 300..302, 2N2218..19A, ++
2N2225	Ge-P	S, 15V, 0,4A, 0,2W, <100/200ns	2a	Cen, Stc	—
2N2226	Si-N	S-L, 50V, 10A, 150W, B>100		USA, Whs	—
2N2227	Si-N	=2N2226: 100V		USA, Whs	—
2N2228	Si-N	=2N2226: 150V		USA, Whs	—
2N2229	Si-N	=2N2226: 200V		USA, Whs	—
2N223	Ge-P	NF, -/18V, 0,15A, 0,25W	37e	Csr, Etc	AC 125..126, AC 151
2N2230	Si-N	S-L, 50V, 10A, 150W, B>350		USA, Whs	—
2N2231	Si-N	=2N2230: 100V		USA, Whs	—
2N2232	Si-N	=2N2230: 150V		USA, Whs	—
2N2233	Si-N	=2N2230: 200V		USA, Whs	—
2N2234	Si-N	NF/S-L, 40V, 0,5A, 10W(Tc=50°), >50MHz	23a	Itt, Sty	—
2N2235	Si-N	=2N2234: >100MHz	23a	Itt, Sty	—
2N2236	Si-N	NF/S, 40V, 0,5A, 0,6W, >50MHz	2a	USA	BC 140..141, BC 300..302, 2N2218..19, ++
2N2237	Si-N	=2N2236: >100MHz	2a	USA	BC 140..141, BC 300..302, 2N2218..19, ++
2N2236	Ge-P	HF, 30V, 0,05A, 0,3W, >400MHz	2a	Cen	AF 139, AF 239(S), 2N3283..86
2N2239	Si-N	NF-Tr/E, 60V, 0,5A, 2,5MHz	43m	Sca, Ssi	(BD 137, BD 167, BD 517, BD 827, ++)
2N224	Ge-P	NF/S, 25V, 0,15A, 0,25W	37e	Csr, Etc	AC 125..126, AC 151..152
2N2240	Si-N	NF/S, 25V, 0,5A, 0,6W, >50MHz, B>40	2a	USA	BC 140..141, BC300..302, 2N3053, ++
2N2241	Si-N	=2N2240: B>100	2a	USA	BC 140..141, BC300..302, 2N3053, ++
2N2242	Si-N	S, 40V, 0,225A, 0,36W, <30/50ns	2a	USA, Fch, Mot	BSS 10..11, BSX19..20, 2N2368..69(A), ++
2N2243(A)	Si-N	NF/S, 120V, 1A, 0,8W, >50MHz	2a	USA, Mic, Tix	BC 300, 2N1893(A), 2N2102, 2N2405, ++
2N2244	Si-N	Uni, 20V, 0,1A, 0,5W, >60MHz, B>5	2a	Nsc, Sty	BC 186, BC 183, BC 236, BC 548, ++
2N2245	Si-N	=2N2244: B>10	2a	Nsc, Sty	BC 186, BC 183, BC 236, BC 548, ++
2N2246	Si-N	=2N2244: B>20	2a	Nsc, Sty	BC 168, BC 183, BC 236, BC 548, ++
2N2247	Si-N	Uni, 45V, 0,1A, 0,5W, >60MHz, B>5	2a	Nsc, Sty	BC 167, BC 182, BC 237, BC 547, ++
2N2248	Si-N	=2N2247: B>10	2a	Nsc, Sty	BC 187, BC 182, BC 237, BC 547, ++
2N2249	Si-N	=2N2247: B>20	2a	Nsc, Sty	BC 187, BC 182, BC 237, BC 547, ++
2N225	Ge-P	=2x2N224 gep.	37e	Csr, Etc	AC 125..126, AC 151..152
2N2250	Si-N	Uni, 25V, 0,1A, 0,5W, >60MHz, B>5	2a	Nsc, Sty	BC 168, BC 183, BC 236, BC 548, ++
2N2251	Si-N	=2N2250: B>10	2a	Nsc, Sty	BC 186, BC 183, BC 236, BC 548, ++
2N2252	Si-N	=2N2250: B>20	2a	Nsc, Sty	BC 168, BC 183, BC 236, BC 548, ++
2N2253	Si-N	Uni, 50V, 0,1A, 0,5W, >80MHz, B>5	2a	Nsc, Sty	BC 167, BC 182, BC 237, BC 547, ++
2N2254	Si-N	=2N2253: B>10	2a	Nsc, Sty	BC 167, BC 182, BC 237, BC 547, ++
2N2255	Si-N	=2N2253: B>20	2e	Nsc, Sty	BC 187, BC 182, BC 237, BC 547, ++
2N2256	Si-N	SS, 7V, 0,1A, 0,3W, <7/7ns, B>20	2a	USA, Mot	—
2N2257	Si-N	=2N2256: B>40	2a	USA, Mot	—
2N2258	Ge-P	SS, 7V, 0,1A, 0,15W, <7/7ns, B>20	2a	USA, Mot	—
2N2259	Ge-P	=2N2258: B>40	2a	USA, Mot	—
2N226	Ge-P	NF/S, 30V, 0,15A, 0,25W	37a	Csr, Etc	AC 125..126, AC 151..152
2N2260	GTO-Thy	30V, 0,2A, Igt<0,26mA			—
2N2261	GTO-Thy	=2N2260: Igt<0,5mA			—
2N2262	GTO-Thy	=2N2260: Igt<5mA			—
2N2266	Ge-P	S-L, 80V, 5A, 50W	≈37b	USA	—
2N2267	Ge-P	=2N2266: 100V	≈37b	USA	—
2N2268	Ge-P	=2N2266: Iso	≈37b	USA	—
2N2269	Ge-P	=2N2267: Iso	≈37b	USA	—
2N227	Ge-P	=2x2N226 gep.	37a	Csr, Etc	AC 125..126, AC 151..152
2N2270(L,S)	Si-N	NF/S, 60V, 1A, 1W, 250MHz	2a	USA, EUR	BC 140..141, 2N1990, 2N2218..19(A), ++
2N2271	Ge-P	NF/S, 20V, 0,5A, 0,25W	2a(B=case)	USA	AC 128, AC 152..153, AC 186, 2SB405
2N2272	Si-N	S, 40V, 0,5A, 0,36W, <40/40ns	2a	Cen, Sty	BSS 10, BSX26, BSX39, 2N4013..14
2N2273	Ge-P	HF, 25V, 0,1A, 0,15W, >250MHz	2a	USA, Mot	AFY 18, 2N3323..25, (AF 106, AF 109R)
2N2274	Si-P	Chopper, 25/25/25V, 0,05A, 0,15W	2a	USA	2N2946
2N2275	Si-P	=2x2N2274 gep	2a	USA	2x2N2946
2N2276	Si-P	Chopper, 15/10/10V, 0,05A, 0,15W	2a	USA	2N2945
2N2277	Si-P	=2x2N2276 gep	2a	USA	2x2N2945
2N2278	Si-P	Chopper, 15/15/15V, 0,05A, 0,15W	2a	USA	2N2945
2N2279	Si-P	=2x2N2278 gep	2a	USA	2x2N2945
2N228	Ge-N	NF/S, 40V, 0,1A, 0,18W	2a	Csr, Etc	(AC 127)
2N2280	Si-P	Chopper, 10/6/10V, 0,05A, 0,15W	2a	USA	2N2944
2N2281	Si-P	=2x2N228 gep	2a	USA	2x2N2944
2N2282	Ge-P	S-L, 60V, 3A, 5W, >20MHz	43m	USA	—
2N2283	Ge-P	=2N2282 100V	43m	USA	—
2N2284	Ge-P	=2N2282: 200V	43m	USA	—
2N2285	Ge-P	NF/S-L, 60V, 25A, 106W	23a	USA, Mot	2N1651..53
2N2286	Ge-P	=2N2285: 100V	23a	USA, Mot	2N1652..53

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2N2287	Ge-P	=2N2285: 120V	23a	USA, Mot	2N1653
2N2288	Ge-P	NF/S-L, 40V, 10A, 70W, B>20	23a	USA, Mot	AL100..101, AUY21, 2N1549..1560,++
2N2289	Ge-P	=2N2288: 80V	23a	USA, Mot	AL100..101, AUY37, 2N1559..1560,++
2N229	Ge-N	NF/S, 18V, 0,25A, 0,18W	2a	Csr,Etc	(AC127, ASY28..29, ASY73..75)
2N2290	Ge-P	=2N2288: 120V	23a	USA, Mot	AL100, AUY38, 2N2527..28
2N2291	Ge-P	NF/S-L, 40V, 10A, 70W, B>50	23a	USA, Mot	AL100..101, AUY21, 2N1549..1560,++
2N2292	Ge-P	=2N2291: 80V	23a	USA, Mot	AL100..101, AUY37, 2N1559..1560,++
2N2293	Ge-P	=2N2291: 120V	23a	USA, Mot	AL100, AUY38, 2N2527..28
2N2294	Ge-P	NF/S-L, 40V, 10A, 60W	23a	USA	AL100..101, AUY21, 2N2288..93,++
2N2295	Ge-P	=2N2294: 80V	23a	USA	AL100..101, AUY37, 2N2292..93,++
2N2296	Ge-P	=2N2294: 120V	23a	USA	AL100, AUY38, 2N2293, 2N2527..28
2N2297(S)	Si-N	Uni, 80V, 1A, 0,8W, 10MHz	2a	USA,EUR	BC140..141, BSX45..47, 2N1990,++
2N23	Ge-P	NF/S, 40V, 0,04A, 0,08W		Wes	(ACY38, ASY48, ASY77, 2N2042..43)
2N230	Ge-P	NF-L, 60V, 2A, 15W	2a	Mal	AUY18, AUY35..38
2N2303	Si-P	NF/S, 50V, 0,5A, 0,6W, >60MHz	2a	USA,EUR	BC161, BC303..304, BC381, 2SA608,++
2N2304	Si-N	NF/S-L, 80V, 3A, 25W	2a	USA	(BD241A, BD535, BD539A, BD935,++)
2N2305	Si-N	NF/S-L, 60V, 6A, 75W	23a	USA	BD245A, BDV91, BDX91, 2N4914..15,++
2N2306	Si-N	S-L, 75V, 2A, 13W, >175MHz	2a	Trw	(BD138, BD230, BD379, 2SD1177..78,++)
2N2307	UJT-P	0,25W, Ip<2μA, Rbb<9,1kΩ		Inr	—
2N2308	Si-N	S-L, 100V, 3A, 25W, >1MHz	2a	USA	(BD241C, BD539C, BD937, 2SD712,++)
2N2309	Si-N	Uni, 30V, 0,6A, 40MHz	2a	USA	BC140..141, BC300..302, 2N3053,++
2N231	Ge-P	HF, 4,5V, 3mA, 9mW, 20MHz	37d	Csr	AF124..127, AF200
2N2310	Si-N	Uni, 80V, 0,5A, 0,35W, 40MHz, B>12	2a	USA	BC337A, BC637, BC638, 2SD667,++
2N2311	Si-N	=2N2310: 100V	2a	USA	BC639, BCX24, 2N3700..01, 2SD667,++
2N2312	Si-N	Uni, 60V, 0,5A, 0,35W, 40MHz, B>30	2a	USA	BC337A, BC637, BC638, 2SD667,++
2N2313	Si-N	=2N2312: 100V	2a	USA	BC639, BCX24, 2N3700..01, 2SD667,++
2N2314	Si-N	Uni, 80V, 0,5A, 0,35W, >40MHz, B>20	2a	USA	BC337A, BC637, BC639, 2SD667,++
2N2315	Si-N	Uni, 80V, 0,5A, 0,35W, >50MHz, B>40	2a	USA	BC337A, BC637, BC639, 2SD667,++
2N2316	Si-N	Uni, 120V, 0,5A, 0,35W, >50MHz, B>40	2a	USA	BCX22, 2N3700..01, 2SC2235, 2SD667,++
2N2317	Si-N	Uni, 75V, 0,5A, 0,35W, >60MHz, B>40	2a	USA	BC639, BCX24, 2N3700..01, 2SD667,++
2N2318	Si-N	S, 30V, 0,2A, 0,38W, 45/40ns	2a	USA	BSS11..12, BSX19..20, 2N2388..69(A),++
2N2319	Si-N	=2N2318: 0,3W	2a	USA, Mot	BSS11..12, BSX19..20, 2N2388..69(A),++
2N232	Ge-P	HF, 4,5V, 3mA, 9mW, 30MHz	37d	Csr,Sty	AF124+F11646..127, AF200
2N2320	Si-N	=2N2318: 0,6W	2a	USA	BSS28..29, BSV69, 2N3724(A), 2SC1385++
2N2322	50Hz-Thy	25V, 1A(Tc=85°), Igt/Ih<0,2/<2mA	2a	USA,Mot,Tix	2N6332, TAG815-100, (MCR606-2)
2N2322A	50Hz-Thy	=2N2322: Igt/Ih<0,02/<2mA	2a		—
2N2323	50Hz-Thy	=2N2322: 50V	2a		2N6333, TAG615-100, (MCR606-2)
2N2323A	50Hz-Thy	=2N2323: Igt/Ih<0,02/<2mA	2a		—
2N2324	50Hz-Thy	=2N2322: 100V	2a		2N6334, TAG615-100, (MCR606-3)
2N2324A	50Hz-Thy	=2N2324: Igt/Ih<0,02/<2mA	2a		—
2N2325	50Hz-Thy	=2N2322: 150V	2a		2N6335, TAG815-200, (MCR606-4)
2N2325A	50Hz-Thy	=2N2325: Igt/Ih<0,02/<2mA	2a		—
2N2326	50Hz-Thy	=2N2322: 200V	2a		2N6335, TAG615-200, (MCR606-4)
2N2326A	50Hz-Thy	=2N2326: Igt/Ih<0,02/<2mA	2a		—
2N2327	50Hz-Thy	=2N2322: 250V	2a		2N6336, TAG615-300, (MCR606-5)
2N2327A	50Hz-Thy	=2N2327: Igt/Ih<0,02/<2mA	2a		—
2N2328	50Hz-Thy	=2N2322: 300V	2a		2N6336, TAG615-300, (MCR606-5)
2N2328A	50Hz-Thy	=2N2328: Igt/Ih<0,02/<2mA	2a		—
2N2329	50Hz-Thy	=2N2322: 400V	2a		2N6337, TAG815-400, (MCR606-6)
2N2329A	50Hz-Thy	=2N2329: Igt/Ih<0,02/<2mA	2a		—
2N233	Ge-N	HF, 10V, 0,1A, 0,15W, >2MHz	2a	Csr,Etc	AC127, ASY28..29, ASY73..75
2N2330(S)	Si-N	Chopper, 30V, 0,5A, 0,8W, >100MHz	2a	USA, Mot	—
2N2331(S)	Si-N	=2N2330: 0,5W	2a	USA, Mot	—
2N2332	Si-P	Chopper, 15/5/15V, 0,1A, 0,15W	2a	USA	2N2944
2N2333	Si-P	Chopper, 15/5/15V, 0,1A, 0,15W	2a	USA	2N2944
2N2334	Si-P	Chopper, 30/15/30V, 0,1A, 0,15W	2a	USA	2N2946
2N2335	Si-P	Chopper, 30/15/30V, 0,1A, 0,15W	2a	USA	2N2946
2N2338	Si-P	Chopper, 50/35/50V, 0,1A, 0,15W	2a	USA	2N2946
2N2337	Si-P	Chopper, 50/35/50V, 0,1A, 0,15W	2a	USA	2N2946
2N2338	Si-N	S-L, 80V, 7,5A, 150W	38a	Cen,Ssi	—
2N2339	Si-N	S-L, 60V, 2,5A, 40W		USA	—
2N233A	Ge-N	=2N229: 18V	2a		AC127, ASY28..29, ASY73..75
2N234(A)	Ge-P	NF-L, 30V, 3A, 25W	23a	USA	AD149, AUY19..20, 2N2137..2146,++
2N2340	Si-N	NF-L, 50V, 1A, 15W, B>10	43m	Del	(BD137, BD187, BD228, BD235,++)
2N2341	Si-N	NF-L, 50V, 1A, 15W, B>40	43m	Del	(BD137, BD167, BD228, BD235,++)
2N2342	Si-N	=2N2340 100V	43m	Del	(BD139, BD169, BD230, BD237,++)

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2N2343	Si-N	=2N2341: 100V	43m	Del	(BD139, BD169, BD230, BD237,++)
2N2344	50Hz-Thy	25V, 1A(Tc=55°), Igt/Ih<0,02/<1mA	2a	Gen,Mot,Tag	2N2322A
2N2345	50Hz-Thy	=2N2344: 50V	2a	–	2N2323A
2N2346	50Hz-Thy	=2N2344: 100V	2a		2N2324A
2N2347	50Hz-Thy	=2N2344: 150V	2a		2N2325A
2N2348	50Hz-Thy	=2N2344: 200V	2a		2N2326A
2N2349	Si-N	HF, 40V, 0,025A, 0,15W	2a	USA	BF198..199, BF224..225, BF598..597,++
2N235(A,B)	Ge-P	NF-L, 50V, 3A, 25W	23a	USA	AD149, AUY19..20, 2N2144..2146,++
2N2350(A)	Si-N	Uni, 60V, 1A, 0,4W, >50MHz	2a	USA	BC337A, BC637, BC639, 2SD667,++
2N2351(A)	Si-N	Uni, 60V, 1A, 0,4W, >50MHz	2a	USA	BC639, BCX24, 2N3700..01, 2SD667,++
2N2352(A)	Si-N	Uni, 60V, 1A, 0,4W, >50MHz	2a	USA	BC337A, BC637, BC639, 2SD667,++
2N2353(A)	Si-N	Uni, 45V, 1A, 0,4W, >50MHz	2a	USA	BC337(A), BC635, BC637, BC639,++
2N2354	Ge-N	NF, 20V, 0,25A, 0,18W	2a	Ssi	AC127, ASY28..29, ASY73..75
2N2356(A)	Si-N	Dual-Chopper, 25V, 0,5A, 0,6W	TO-77	USA,Gen,Tho	—
2N2357	Ge-P	S-L, 60V, 50A, 170W	23a	USA,Mot	2N4280..83, 2N5435..40
2N2358	Ge-P	=2N2357: 100V	23a	USA,Mot	2N5436, 2N5439
2N2359	Ge-P	=2N2357: 120V	23a	USA,Mot	2N5437, 2N5440
2N236(A,B)	Ge-P	NF-L, 50V, 3A, 25W	23a	USA	AD149, AUY19..20, 2N2144..2146,++
2N2360	Ge-P	VHF, 20V, 0,05A, 0,06W	5g	Spr	AF139, AF239(S), 2N3283..86
2N2361	Ge-P	VHF, 20V, 0,05A, 0,06W	5g	Spr	AF139, AF239(S), 2N3283..66
2N2362	Ge-P	VHF, 20V, 0,05A, 0,06W	5g	Spr	AF139, AF239(S), 2N3263..86
2N2363	Ge-P	VHF, 30V, 0,05A, 0.075W	5g	Idi	AF139, AF239(S), 2N3283..86
2N2364(A)	Si-N	Uni, 120V, 1A, 0,4W, >50MHz	2a	USA	BCX22, 2N3700..01, 2SC2235, 2SD667,++
2N2368	Si-N	SS, 40V, 0,2A, 0,36W, <12/15ns, B>20	2a	USA,EUR,Mic	BSS10..11, BSX19..20, 2N3261, 2SC2901
2N2369(A)	Si-N	=2N2368: B>40	2a	USA,EUR,Mic	BSS10..11, BSX19..20, 2N3261, 2SC2901
2N237	Ge-P	NF, 45V, 0,02A, 0,15W	2a	Csr,Etc	2SB56A
2N2370	Si-P	Chopper, 15/15/15V, 0,05A, 0,2W	2a	USA	2N2945
2N2371	Si-P	Chopper, 15/15/15V, 0,05A, 0,2W	2a	USA	2N2945
2N2372	Si-P	=2N2370: 0,15W	2a	USA	2N2945
2N2373	Si-P	=2N2371: 0,15W	2a	USA	2N2945
2N2374	Ge-P	NF-Tr, 35/35/35V, 0,5A, 0,25W, 15MHz	2a	USA	(ASY78..77)
2N2375	Ge-P	NF-Tr, 35/35/35V, 0,5A, 0,25W, 9MHz	2a	USA	(ASY78..77)
2N2376	Ge-P	=2N2375: gep	2a	USA	(ASY76..77)
2N2377	Si-P	HF/S, 25V, 0,05A, 0,15W, >8MHz	2a	USA	BC213, BC258, BC308, BC558,++
2N2378	Si-P	HF/S, 10V, 0,05A, 0,15W, >8MHz	2a	USA	BC213, BC258, BC308, BC558,++
2N2379	Ge-P	S-L, 100V, 15A, 150W	38a	old	2N2493
2N238	Ge-P	NF, 30V, 0,5A, 0,05W	3a	Csr,Etc	AC125..126, AC151, 2SB54, 2SB56
2N2380(A)	Si-N	NF/S, 60V, 0,5A, 0,6W, >100MHz	2a	USA	BC140..141, BC300..301, 2N2218..19A,++
2N2381	Ge-P	S, 30V, 0,5A, 0,3W, >300MHz	2a	Mot,Sty	—
2N2382	Ge-P	=2N2381: 45V	2a	Mot,Sty	—
2N2383	Si-N	NF/S-L, 60V, 2A, 85W		USA	2N1722..23, (BD243B, BD539B, BD951++)
2N2384	Si-N	NF/S-L, 60V, 5A, 85W	49m	USA	2N3487..92, (BD243B, BD539B, BD951++)
2N2386(A)	P-FET	Uni, 20V, Idss=0,9..15mA, Up<8V	2a	Sol,Tix	2N2497..2500
2N2387	Si-N	NF, ra, 45V, 0,03A, 0,3W, >30MHz, B>40	24b	Tix	BC382..384, BC413..414, BC550,++
2N2388	Si-N	=2N2387: B>100	24b	Tix	BC382..384, BC413..414, BC550,++
2N2389	Si-N	NF/S, 75V, 0,5A, 0,45W, >60MHz, B>40	24b	Tix	BC639, 2SD667, 2SD774, 2SD1226,++
2N2390	Si-N	=2N2389: >70MHz, B>100	24b	Tix	BC839, 2SD667, 2SD774, 2SD1226,++
2N2391	Si-P	Uni, 25V, 0,05A, 0,3W, 100MHz, B>15	24b	Tix	BC213, BC258, BC308, BC553,++
2N2392	Si-P	=2N2391: B>30	24b	Tix	BC213, BC258, BC308, BC558,++
2N2393	Si-P	Uni, 50V, 0,3A, 0,45W, >50MHz, B>20	24b	Tix	BC327(A), BC638, BC640, 2SB647,++
2N2394	Si-P	=2N2393: >60MHz, B>30	24b	Tix	BC327(A), BC638, BC640, 2SB647,++
2N2395	Si-N	NF/S, 60V, 0,3A, 0,45W, >40MHz, B>20	24b	Tix	BC337A, BC637, BC639, 2SD667,++
2N2396	Si-N	=2N2395: >50MHz, B>40	24b	Tix	BC337A, BC637, BC639, 2SD667,++
2N2397	Si-N	S, 35V, 0,2A, 0,3W, <40/70ns	24b	Syl	BSS10..11, BSX19..20, 2N2368..69(A),++
2N2398	Ge-P	VHF/UHF, 20V, 0,05A, 0,06W	5g	Sem,Spr	AF139, AF239(S), 2N3263..66
2N2399	Ge-P	VHF/UHF, 20V, 0,05A, 0,06W	5g	Sem,Spr	AF139, AF239(S), 2N3263..66
2N24	Ge-P	NF/S, 30V, 0,025A, 0,12W		Wes	(ACY39, ASY48, ASY77, 2N2042..43)
2N240	Ge-P	HF, 8V, 15mA, 0,03W, >30MHz	37d	USA	AF124..127, AF200
2N2400	Ge-P	S, 12V, 0,1A, 0,15W, >150MHz	2a	USA	2N980..987, 2N2635, 2N2955..57
2N2401	Ge-P	S, 15V, 0,1A, 0,15W, >200MHz	2a	USA	2N705(A), 2N964(A), 2N2635, 2N2955..57
2N2402	Ge-P	S, 18V, 0,1A, 0,15W, >250MHz	2a	USA	2N2635, 2N2955..57
2N2403	Si-N	S, 60V, 1A, 150MHz, B>20	2a	Nsc	BSW27..26, BSX59..61, 2N3252..53,++
2N2404	Si-N	=2N2403: B>40	2a	Nsc	BSW27..26, BSX59..61, 2N3252..53,++
2N2405(L,S)	Si-N	NF/S, 140V, 1A, 1W, >120MHz	2a	USA,EUR	2N2102, 2N3019..3020
2N241(A)	Ge-P	NF, 25V, 0,2A, 0,1..0,2W	1a	USA	AC125..126, AC151, 2SB54, 2SB56
2N2410	Si-N	S, 60V, 0,8A, 0,8W, 35/40ns	2a	USA,EUR	BSS27, BSV77, BSV95, 2N5189,++

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2N2410/51	Si-N	=2N2410: 0,3W	24b	Syl	BSS27, BSV77, BSV95, 2N5189, ++
2N2411	Si-P	S, 25V, 0,1A, 0,3W, 15/74ns, B>20	2a	USA, Phi, Tix	BSX36
2N2412	Si-P	=2N2411: B>40	2a	USA, Phi, Tix	BSX36
2N2413	Si-N	HF/S, 40V, 0,2A, 0,3W, >300MHz	2a	Sty, Tix	BSS10..11, BSX19..20, 2N2368..69(A), ++
2N2414	Si-N	Dual, 60V, 0,5A, 0,6W, >60MHz	TO-77	USA	BFX70..72, 2N2060, 2N2223
2N2415	Ge-P	VHF/UHF, 15V, 0,02A, 0,075W, >550MHz	5g	USA, Mot, Tix	AF139, AF239(S), 2N3283..86
2N2416	Ge-P	VHF/UHF, 15V, 0,02A, 0,075W, >400MHz	5g	USA, Mot, Tix	AF139, AF239(S), 2N3283..86
2N2417	UJT-P	=2N489: 0,3W	5e	Gen	→2N489
2N2418	UJT-P	=2N490: 0,3W	5e	Gen	→2N490
2N2419	UJT-P	=2N491: 0,3W	5e	Gen	→2N491
2N242	Ge-P	NF/S-L, 45V, 5A, 106W	23a	USA	AL102..103, AUY28, 2N1539..46, ++
2N2420	UJT-P	=2N492: 0,3W	5e	Gen	→2N492
2N2421	UJT-P	=2N493: 0,3W	5e	Gen	→2N493
2N2422	UJT-P	=2N494: 0,3W	5e	Gen	→2N494
2N2423	Ge-P	S-L, 100V, 5A, 90W	23a	USA	AL102..103, AUY37, 2N1547..48, ++
2N2424	Si-P	NF/S, 40V, 0,05A, 0,375W, <300/500ns	2a	USA	BC212, BC307, BC557, BCY77, BCY79++
2N2425	Si-P	NF/S, 50V, 0,05A, 0,375W, <500/725ns	2a	USA	BC212, BC307, BC557, BCY77, BCY79++
2N2426	Ge-N	NF/S, 40V, 0,2A, 0,15W, >25MHz	2a	Stc, Sty	—
2N2427	Si-N	Uni, 40V, 0,05A, 0,5W, 50MHz	2a	USA	BC167, BC182, BC237, BC547, ++
2N2428	Ge-P	NF, 32V, 0,1A, 0,165W	2a	Amp, Phc	AC125..126, AC151, 2SB54, 2SB56
2N2429	Ge-P	NF, 32V, 0,1A, 0,165W	2a	Amp, Phc	AC125..126, AC151, 2SB54, 2SB56
2N243	Si-N	NF/HF, 60V, 0,06A, 0,75W, β>9	≈1a	USA	(BC140..141, BC300..302, BC637, ++)
2N2430	Ge-N	NF-Tr, 32V, 0,5A, 0,28W	2a	Amp, Phc	AC127, AC176, AC187
2N2431(MP)	Ge-P	NF-Tr, 32V, 0,5A, 0,225W	2a	Amp, Phc	AC128, AC152..153, 2SB324, 2SB415
2N2432	Si-N	Chopper, 30V, 0,1A, 0,3W, >20MHz	2a	USA, Tix	2N4136
2N2432A	Si-N	=2N2432: 45V	2a	USA, Tix	2N4136
2N2433	Si-N	Uni, 75V, 1A, 0,5W, >60MHz, B>40	2a	Sca, Ssi	BC639, BCX24, 2N3700..01, 2SD667, ++
2N2434	Si-N	Uni, 75V, 1A, 0,5W, >90MHz, B>100	2a	Sca, Ssi	BC639, BCX24, 2N3700..01, 2SD667, ++
2N2435	Si-N	Uni, 120V, 0,5A, 0,5W, >60MHz, B>40	2a	Sca, Ssi	BCX22, 2N3700..01, 2SC2235, 2SD667, ++
2N2436	Si-N	Uni, 120V, 0,5A, 0,5W, >90MHz, B>100	2a	Sca, Ssi	BCX22, 2N3700..01, 2SC2235, 2SD667, ++
2N2437	Si-N	Uni, 100V, 0,5A, 0,5W, >70MHz, B>15	2a	Sca, Ssi	BC639, BCX24, 2N3700..01, 2SD667, ++
2N2438	Si-N	=2N2436: >80MHz, B>35	2a	Sca, Ssi	BC639, BCX24, 2N3700..01, 2SD667, ++
2N2439	Si-N	=2N2438: >90MHz, B>75	2a	Sca, Ssi	BC639, BCX24, 2N3700..01, 2SD667, ++
2N244	Si-N	=2N243: β>25	≈1a	USA	(BC140..141, BC300..302, BC637, ++)
2N2440	Si-N	NF/S, 120V, 0,5A, 0,8W, >90MHz	2a	USA	BC300, 2N2102, 2N2405, 2N3019..3020
2N2443	Si-N	NF/S, 120V, 0,8W, >50MHz	2a	USA, Fch	BC300, 2N2102, 2N2405, 2N3019..3020
2N2444	Ge-P	S-L, 80V, 10A, 85W	23a	USA	AL100..101, AUY37, 2N2292..93, ++
2N2445	Ge-P	S-L, 100V, 15A, 90W	23a	USA	2N1552, 2N1556, 2N1560
2N2446	Ge-P	S-L, 60V, 7A, 90W	23a	Cen	AL102..103, AUY22, 2N3615..16, ++
2N2447	Ge-P	NF, 45V, 0,1A, 0,075W	37b	Ray	2N1191..94, 2SB56A
2N2448	Ge-P	NF, 45V, 0,1A, 0,075W		Ray	2N1191..94, 2SB56A
2N2449	Ge-P	NF, 35V, 0,1A, 0,075W	37b	Ray	AC125..125, AC151, 2SB54, 2SB56
2N2450	Ge-P	NF, 35V, 0,1A, 0,075W		Ray	AC125..125, AC151, 2SB54, 2SB56
2N2451	Ge-P	HF/S, 6/5/6V, 0,05A, 0,025W, >80MHz	37d	Spr	—
2N2452	Opto				—
2N2453	Si-N	Dual, 60V, 0,05A, 0,3W, >60MHz	TO-77	USA, EUR, Mic	2N2060, 2N2223, 2N2919..20
2N2453A	Si-N	=2N2453: 60V	TO-77		2N2060, 2N2223
2N2455	Ge-P	S, 15V, 0,2A, 0,15W, >600MHz, <-/65ns	2a	Ssi	—
2N2456	Ge-P	S, 15V, 0,2A, 0,15W, >1000MHz, <-/85ns	2a	Ssi	—
2N2457	FET	Up<5V	2	Fch	—
2N2458	FET	Up<5V	24	Fch	—
2N2459	Si-N	Uni, 100V, 0,05A, 0,4W, >100MHz, β+C11862>40	2a	USA	BSS36, BSX21, 2SC2240, 2SC2459, ++
2N2460	Si-N	=2N2459: >120MHz, β>70	2a	USA	BSS36, BSX21, 2SC2240, 2SC2459, ++
2N2461	Si-N	=2N2459: >140MHz, β>115	2a	USA	BSS36, BSX21, 2SC2240, 2SC2459, ++
2N2462	Si-N	=2N2459: >160MHz, β>160	2a	USA	BSS36, BSX21, 2SC2240, 2SC2459, ++
2N2463	Si-N	Uni, 100V, 0,05A, 0,5W, >100MHz, β>40	2a	USA	BSS36, BSX21, 2SC2240, 2SC2459, ++
2N2464	Si-N	=2N2463: >120MHz, β>70	2a	USA	BSS36, BSX21, 2SC2240, 2SC2459, ++
2N2465	Si-N	=2N2463: >140MHz, β>115	2a	USA	BSS36, BSX21, 2SC2240, 2SC2459, ++
2N2466	Si-N	=2N2463: >160MHz, β>160	2a	USA	BSS36, BSX21, 2SC2240, 2SC2459, ++
2N2467	Ge-P	NF/S, 60V, 3A, >20MHz	2a	Sol, Stc	—
2N2468	Ge-P	=2N2467: 100V	2a	Sol, Stc	—
2N2469	Ge-P	=2N2467: 200V	2a	Sol, Stc	—
2N247	Ge-P	HF, 40V, 10mA, 0,08W, 30MHz	1g	Rca, Syl	AF124..127, AF200
2N247/33	Ge-P	=2N247: 0,12W	5g	Syl	AF124..127, AF200
2N2472	Si-N	NF/S, 120V, 1A, >10MHz	43m	Gen, Sca	(BD524, 2SC2364, 2SC2481, 2SD1361..82)
2N2473	Si-N	=2N2472:	5g	Gen	(BD524, 2SC2384, 2SC2481, 2SD1381..82)

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2N2474	Si-P	Chopper, 30V, 0,05A, 0,25W	2a	USA	—
2N2475	Si-N	SS, 15V, 0,1A, 0,3W, <20/15ns	2a	USA,EUR	BSV89..92, BSX44, 2N2368..69(A),++
2N2476	Si-N	S, 60V, 1A, 0,6W, <25/45ns, B>40	2a	USA,EUR	BSS27, BSV77, BSV95, 2N5189,++
2N2477	Si-N	=2N2476: B>20	2a	USA,EUR	BSS27, BSV77, BSV95, 2N5189,++
2N2476	Si-N	NF/S, 120V, 0,5A, 0,6W, >200MHz	2a	USA	BC300, 2N2102, 2N2405, 2N3019..20
2N2479	Si-N	NF/S, 60V, 0,5A, 0,6W, >150MHz	2a	USA	BC140..141, BC300..301, BSW39,++
2N248	Ge-P	HF, 25V, 5mA, 0,03W, 50MHz	2a	Etc,Tix	AF124..127, AF200
2N2480	Si-N	Dual, 75V, 0,5A, 0,6W, >50MHz	TO-77	USA, Mot	BFX70..72, 2N2060, 2N2223
2N2480A	Si-N	=2N2480: 80V	TO-77		BFX70..72, 2N2060, 2N2223
2N2481	Si-N	S, 40V, 0,36W, >300MHz, <40/55ns	2a	USA, Mot	BSS10..11, BSX19..20, 2N2368..69(A),++
2N2482	Ge-N	HF, 20V, 0,1A, 0,15W, >600MHz	2a	USA	—
2N2483	Si-N	NF-ra, 80V, 0,05A, 0,36W, 100MHz, B>40	2a	USA,EUR	2N3117, 2SC1775(A), 2SC2240, 2SC2390,++
2N2484(A)	Si-N	=2N2483: B>100	2a	USA,EUR	2N3117, 2SC1775(A), 2SC2240, 2SC2390,++
2N2485	Si-N	NF/S, 120V, 1A, 8,8W(Tc=25°), >100MHz	2a	Nsc, Sty	BUX49, BUY41, 2SC1860
2N2486	Si-N	=2N2485: 140V	2a	Nsc, Sty	BUX49, BUY41, 2SC1860
2N2487	Ge-P	HF/S, 15V, 0,1A, 0,06W, >360MHz	2a	USA	2N3283..86
2N2488	Ge-P	HF/S, 15V, 0,1A, 0,06W, >360MHz	2a	USA	2N3283..86
2N2489	Ge-P	HF/S, 20V, 0,1A, 0,06W, >300MHz	2a	USA	2N3283..86
2N249	Ge-P	NF, 25V, 0,2A, 0,35W	2a	Csr,Etc	AC125..126, AC151
2N2490	Ge-P	NF/S-L, 70V, 15A, 170W, B>20	38a	USA, Mot	2N1981..82, 2N2075..76, 2N2079..80
2N2491	Ge-P	NF/S-L, 60V, 15A, 170W, B>35	38a	USA, Mot	2N1981..82, 2N2075..76, 2N2079..80
2N2492	Ge-P	NF/S-L, 80V, 15A, 170W, B>25	39a	USA, Mot	2N1982, 2N2075, 2N2079
2N2493	Ge-P	NF/S-L, 100V, 15A, 170W, B>25	38a	USA, Mot	—
2N2494	Ge-P	HF, 40V, 10mA, 0,125W, >135MHz	1g	Amp	AF106, AF109R, AF306, 2N3323..25
2N2495	Ge-P	=2N2494:	5g	Amp	AF106, AF109R, AF306, 2N3323..25
2N2496	Ge-P	=2N2494: 0,1W	5g	Amp	AF106, AF109R, AF306, 2N3323..25
2N2497	P-FET	Uni, 20V, Idss>1mA, Up<5V	2a	Sol,Tix	2N2608, 2N3329, 2N5460
2N2498	P-FET	Uni, 20V, Idss>2mA, Up<6V	2a	Sol,Tix	2N2609, 2N3330, 2N5461
2N2499	P-FET	Uni, 20V, Idss>5mA, Up<8V	2a	Sol,Tix	BF320B, 2N3331, 2N5462
2N25	Ge-P	NF/S, 50V, 0,03A, 0,2W		Wes	(ACY39, ASY48, ASY77, 2N2042..43)
2N250	Ge-P	S-L, 30V, 3A, 25W	23a	USA,Tix	AD149, AUY10..20, 2N2137..46,++
2N2500	P-FET	Uni, 20V, Idss>1mA, Up<6V	2a	Sol,Tix	2N2608, 2N3332, 2N5460
2N2501	Si-N	S, 40V, 0,36W, >350MHz	2a	USA, Mot	BSS10..11, BSX19..20, 2N2368..69(A),++
2N2509	Si-N	Uni, 125V, 0,2A, 0,36W, >45MHz	2a	USA,Fch,Nsc	BFR86, 2SC2240, 2SC2459, 2SC3245(A)
2N250A	Ge-P	S-L, 40V, 7A, 90W	23a		AL102..103, AUY21..22, 2N3611..18,++
2N251	Ge-P	S-L, 80V, 3A, 25W	23a	USA, Tix	AL102..103, AUY19..20, 2N2144..46,++
2N2510	Si-N	Uni, 100V, 0,2A, 0,36W, >45MHz	2a	USA,Fch,Nsc	BFR86, 2SC2240, 2SC2459, 2SC3245(A)
2N2511	Si-N	Uni, 80V, 0,2A, 0,36W, >45MHz	2a	USA,Fch,Nsc	BC546, 2SC2240, 2SC2459, 2SC3245(A)
2N2512	Ge-P	HF, 70V, 0,03A, 0,15W, >140MHz	5g	Amp	(AF118)
2N2514	Si-N	Uni, 80V, 0,1A, 0,4W, 30MHz, B>15	2a	USA,Nsc	BC546, 2SC2240, 2SC2459, 2SC3245(A)
2N2515	Si-N	=2N2514: 60MHz, B>30	2a	USA,Nsc	BC548, 2SC2240, 2SC2459, 2SC3245(A)
2N2516	Si-N	=2N2514: 100MHz, B>60	2a	USA,Nsc	BC546, 2SC2240, 2SC2459, 2SC3245(A)
2N2517	Si-N	Uni, 125V, 0,05A, 0,4W, 30MHz, B>15	2a	USA,Nsc	BSS36, BSX21, 2SC2240, 2SC2459,++
2N2518	Si-N	=2N2517: 60MHz, B>30	2a	USA,Nsc	BSS39, BSX21, 2SC2240, 2SC2459,++
2N2519	Si-N	=2N2517: 100MHz, B>80	2a	USA,Nsc	BSS36, BSX21, 2SC2240, 2SC2459,++
2N251A	Ge-P	S-L, 80V, 7A, 90W	23a		AL102..103, AUY21..22, 2N3614..18,++
2N252	Ge-P	HF, -/16V, 5mA, 0,03W	2a	Csr,Etc	AF124..127, AF200
2N2520	Si-N	Uni, 60V, 0,1A, 0,4W, >50MHz, B>18	2a	USA	BC174, BC182, BC190, BC546,++
2N2521	Si-N	=2N2520: B>36	2a	USA	BC174, BC182, BC190, BC546,++
2N2522	Si-N	=2N2520: B>76	2a	USA	BC174, BC182, BC190, BC546,++
2N2523	Si-N	Uni, ra, 80V, 0,03A, 0,4W, >70MHz, B>60	2a	USA	2N2483..84, 2N3117, 2SC2240, 2SC2390,++
2N2524	Si-N	=2N2523: B>150	2a	USA	2N2483..84, 2N3117, 2SC2240, 2SC2390,++
2N2525	Si-N	HF-L, 100V, 1A, 16W, >56MHz	49a	USA	—
2N2526	Ge-P	S-L, 80V, 10A, 85W	23a	USA, Mot	AL100..101, 2N2289..90, 2N2292..93
2N2527	Ge-P	=2N2526: 120V	23a	USA, Mot	AL100, 2N2290, 2N2293
2N2526	Ge-P	=2N2526: 180V	23a	USA, Mot	—
2N2529	Si-N	Uni, 45V, 0,025A, 0,15W, >6MHz, B>10	2a	Sty	BC167, BC182, BC237, BC547,++
2N253	Ge-N	HF, 30V, 300mA, 0,065W	2a	Csr,Etc	—
2N2530	Si-N	=2N2529: >10MHz, B>12	2a	Sty	BC167, BC182, BC237, BC547,++
2N2531	Si-N	=2N2529: >12MHz, B>20	2a	Sty	BC167, BC182, BC237, BC547,++
2N2532	Si-N	=2N2529: >16MHz, B>45	2a	Sty	BC167, BC182, BC237, BC547,++
2N2533	Si-N	=2N2529: >10MHz, B>20	2a	Sty	BC167, BC182, BC237, BC547,++
2N2534	Si-N	=2N2529: >20MHz, B>45	2a	Sty	BC167, BC182, BC237, BC547,++
2N2535	Ge-P	NF-L, 80V, 3A, 10W	49a	Rca	—
2N2536	Ge-P	=2N2535: 80V	49a	Rca	—
2N2537	Si-N	S, 80V, 0,8A, 0,8W, <40/40, B>50	2a	Mot,Sem,Tix	BSS27, BSV77, BSV95, 2N5189,++

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2N2538	Si-N	=2N2537: B>100	2a	Mot,Sem,Tix	BSS27, BSV77, BSV95, 2N5189, ++
2N2539	Si-N	=2N2537: 0,5W	2a	Mot,Sem,Tix	2N4014
2N254	Ge-N	HF, 30V, 300mA, 0,065W	2a	Csr,Etc	—
2N2540	Si-N	=2N2537: 0,5W, B>100	2a	Mot,Sem,Tix	2N4014
2N2541	Ge-P	NF/S, 30V, 1A, 0,215W, >10MHz	2a	USA	—
2N255	Ge-P	S-L, 15V, 3A, 20W	23a	USA	AD149, AUY19. 20, 2N2137..46, ++
2N2551	Si-P	NF/S, 150V, 1A(ss), 0,4W	2a	USA	BFT28, 2N3636 37, 2N5415
2N2552	Ge-P	=2N1038	2a°	USA,Mot,Tix	→2N1038
2N2553	Ge-P	=2N1039	2a°	USA,Mot,Tix	→2N1039
2N2554	Ge-P	=2N1040	2a°	USA,Mot,Tix	→2N1040
2N2555	Ge-P	=2N1041	2a°	USA,Mot,Tix	→2N1041
2N2556	Ge-P	=2N1038	2a°	USA,Mot,Tix	→2N1038
2N2557	Ge-P	=2N1039	2a°	USA,Mot,Tix	→2N1039
2N2558	Ge-P	=2N1040	2a°	USA,Mot,Tix	→2N1040
2N2559	Ge-P	=2N1041	2a°	USA,Mot,Tix	→2N1041
2N255A	Ge-P	=2N255: 5A	23a		AL102. 103, AUY21..22, 2N1539..48, ++
2N256	Ge-P	S-L, 30V, 3A, 20W	23a	USA	AD149, AUY19. 20, 2N2137 46, ++
2N2560	Ge-P	=2N1042	2a°	USA,Mot,Tix	→2N1042
2N2581	Ge-P	=2N1043	2a°	USA,Mot,Tix	→2N1043
2N2562	Ge-P	=2N1044	2a°	USA,Mot,Tix	→2N1044
2N2563	Ge-P	=2N1045	2a°	USA,Mot,Tix	→2N1045
2N2564(/5)	Ge-P	=2N1042	2a	USA,Mot,Tix	→2N1042
2N2585(/5)	Ge-P	=2N1043	2a	USA,Mot,Tix	→2N1043
2N2566(/5)	Ge-P	=2N1044	2a	USA,Mot,Tix	→2N1044
2N2567(/5)	Ge-P	=2N1045	2a		→2N1045
2N2568	Ge-N	HF-L, 32V, 0,1A, >1400MHz	5g°	Mot	—
2N2569	Si-N	Chopper, 20V, 0,1A, 0,3W, >100MHz	2a	Amp,Phi	2N2432, 2N4138
2N256A	Ge-P	=2N256: 5A	23a		AL102..103, AUY21..22, 2N1539..48, ++
2N257	Ge-P	NF/S-L, 40V, 3A, 30W	23a	USA, Itt	AD149, AUY19..20, 2N2143..46, ++
2N2570	Si-N	Chopper, 20V, 0,1A, 0,3W, >100MHz	2a	Amp,Phi	2N2432, 2N4138
2N2572	Si-N	Chopper, 20V, 0,5A, 0,3W, >100MHz	2a	Amp	—
2N2572	Si-N	Chopper, 20V, 0,5A, 0,3W, >100MHz	2a	Amp	—
2N2573	50Hz-Thy	25V, 17A(Tc=85°), Igt/Ih<40/10mA	23a	Mot,Sld	2N3668
2N2574	50Hz-Thy	=2N2573: 50V	23a		2N3668
2N2575	50Hz-Thy	=2N2573: 100V	23a		2N3668
2N2576	50Hz-Thy	=2N2573: 200V	23a		2N3669
2N2577	50Hz-Thy	=2N2573: 300V	23a		2N3870
2N2578	50Hz-Thy	=2N2573: 400V	23a		2N3670
2N2579	50Hz-Thy	=2N2573: 500V	23a		—
2N258	Si-P	Uni, 30V, 0,05A, 0,25W, β>15	2a	Ray	BC213, BC258, BC308, BC558, ++
2N2580(M)	Si-N	S-L, 400/400V, 10A, 150W, B>10	38a	Del,Stc	—
2N2581	Si-N	=2N2580: B>25	38a	Del,Stc	—
2N2582	Si-N	S-L, 500/500V, 10A, 150W, B>10	38a	Del,Stc	—
2N2583	Si-N	=2N2582: B>25	38a	Del,Stc	—
2N2584	Si-N	S-L, 600/600V, 10A, 150W, B>10	38a	Stc	—
2N2585	Si-N	=2N2584: B>25	38a	Stc	—
2N2586	Si-N	NF-V, ra, 60V, 0,03A, 0,3W, 63MHz	2a	USA,EUR,Mic	2N2483. 84, 2N3117, 2SC2240, 2SC2390, ++
2N2587	Ge-P	UHF, 30V, 0,1A, 0,15W, >320MHz	2a	Mot	2N3283. 86
2N2588	Ge-P	HF, 40V, 0,03A, 0,15W, >75MHz	2a	Tix	AF106, AF109R, AF306
2N2589	Si-N	S-L, 150/150V, 7A, 85W	49m	Stc	2N5542
2N259	Si-P	=2N258: β>32	2a	Ray	BC213, BC258, BC306, BC558, ++
2N2590	Si-P	Uni, 100V, 0,05A, 0,4W, >50MHz, B>40	2a	USA	BSS86, BSV86, 2SA970, 2SB715..16, ++
2N2591	Si-P	=2N2590: >70MHz, B>70	2a	USA	BSS86, BSV86, 2SA970, 2SB715..16, ++
2N2592	Si-P	=2N2590: >90MHz, B>115	2a	USA	BSS86, BSV86, 2SA970, 2SB715..16, ++
2N2593	Si-P	=2N2590: >110MHz, B>160	2a	USA	BSS86, BSV86, 2SA970, 2SB715 16, ++
2N2594	Si-N	NF/S, 60V, 1A, 1W, >40MHz	2a	USA,Tix	BC140..141, 2N1990, 2N2102, 2N2405, ++
2N2595	Si-P	Uni, 80V, 0,05A, 0,4W, >30MHz, B>15	2a	USA	BSS68, BSV68, 2SA970, 2SB715..16, ++
2N2596	Si-P	=2N2595: >40MHz, B>30	2a	USA	BSS68, BSV68, 2SA970, 2SB715..16, ++
2N2597	Si-P	=2N2595: >60MHz, B>60	2a	USA	BSS86, BSV68, 2SA970, 2SB715..16, ++
2N2598	Si-P	Uni, 125V, 0,05A, 0,4W, >30MHz, B>20	2a	USA	BF398, 2SA970, 2SA1049, 2SB716(A), ++
2N2599(A)	Si-P	=2N2598: >40MHz, B>40	2a	USA	BF398, 2SA970, 2SA1049, 2SB716(A), ++
2N26	Ge-P	NF/S, 40V, 0,04A, 0,09W		Wes	(ACY39, ASY48, ASY77, 2N2042..43)
2N250	Si-P	Uni, 10V, 0,05A, 0,2W	≈2e	Clv	BC213, BC258, BC306, BC558, ++
2N2600(A)	Si-P	=2N2598: >60MHz, B>60	2a	USA	BF398, 2SA970, 2SA1049, 2SB716(A), ++
2N2601	Si-P	Uni, 50V, 0,05A, 0,4W, >20MHz, B>18	2a	USA	BSS86, BSV86, 2SA970, 2SB715..718, ++
2N2602	Si-P	=2N2601: >40MHz, B>38	2a	USA	BSS68, BSV86, 2SA970, 2SB715..716, ++

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2N2603	Si-P	=2N2601: >60MHz, B>76	2a	USA	BSS68, BSV68, 2SA970, 2SB715..716, ++
2N2604	Si-P	NF/S, ra, 60V, 0,03A, 0,4W, >30MHz	2a	USA,EUR,Mic	2SA970, 2SA1016, 2SA1038..39, 2SA1136, ++
2N2605(A)	Si-P	NF/S, ra, 60V, 0,03A, 0,4W, >30MHz	2a	USA,EUR,Mic	2SA970, 2SA1016, 2SA1038..39, 2SA1136, ++
2N2606	P-FET	Uni, 30V, Idss>0,1mA, Up<4V	2a	USA,Mot,Tix	2N5797
2N2607	P-FET	Uni, 30V, Idss>0,3mA, Up<4V	2a	USA,Mot,Tix	2N5020
2N2608	P-FET	Uni, 30V, Idss>0,9mA, Up<4V	2a	USA,Mot,Tix	2N5460
2N2609	P-FET	Uni, 30V, Idss>2mA, Up<4V	2a	USA,Mot,Tix	2N5461
2N260A	Si-P	=2N260: 30V	≈2e		BC213, BC258, BC308, BC558, ++
2N261	Si-P	Uni, 75V, 0,05A, 0,2W	≈2a	Clv	BC212, BC256, BC266, BC556, ++
2N2610	Si-N	NF/S, 45V, 0,025A, 0,15W	≈1a	USA	BC167, BC182, BC237, BC547, ++
2N2611	Si-N	NF/S, 120V, 1A, >4MHz	43m	Sca,Ssi	(BD424, BD524, 2SC2384, 2SC2481, ++)
2N2612	Ge-P	NF/S-L, 65V, 15A, 75W	23a	USA	2N1551..52, 2N1555..56, 2N1559..F1196960
2N2613	Ge-P	NF, 30V, 0,05A, 0,12W	2a	Rca,Spe	AC125..126, AC151, 2SB54, 2SB56
2N2614	Ge-P	NF, 40V, 0,05A, 0,12W	2a	Rca,Spe	2N1191..94, 2SB56A
2N2615	Si-N	VHF/ZF, 30V, 0,3W, >500MHz	2a	USA,Sgs	BF224..225, BFR37, BFW30, BFX73, ++
2N2616	Si-N	VHF/ZF, 30V, 0,05A, 0,3W, >600MHz	2a	USA,Sgs	BF224..225, BFR37, BFW30, BFX73, ++
2N2617	Si-N	NF, 25V, 0,1A, 0,25W	1a	Phc	BC166, BC183, BC238, BC548, ++
2N2618	Si-N	Uni, 60V, 0,75A, 0,6W, >200MHz	2a	Syl	BC140..141, BC300..302, 2N2218..19, ++
2N2618/46	Si-N	=2N2618: 0,4W	2a		BC337A, BC637, BC639, 2SD667, ++
2N262	Si-P	Uni, 10V, 0,05A, 0,2W	≈2e	Civ	BC213, BC258, BC308, BC558, ++
2N2620	N-FET	Uni, 50V, Idss<50mA, Up<20V	2b	Tdy	—
2N2621	Ge-P	NF/HF, 15V, 0,1A, 0,15W, >13MHz, B>15	2a	Cen,Sty	ASY26..27, 2N1309
2N2622	Ge-P	=2N2621: 24V, >15MHz, B>15	2a	Cen,Sty	ASY26..27, 2N1309
2N2623	Ge-P	=2N2621: 32V, >16MHz, B>20	2a	Cen,Sty	ASY26, 2N1309
2N2624	Ge-P	NF/HF, 16V, 0,1A, 0,15W, >13MHz, B>15	2a	Cen,Sty	ASY26..27, 2N1309
2N2625	Ge-P	=2N2624: 24V, >15MHz, B>15	2a	Cen,Sty	ASY26..27, 2N1309
2N2626	Ge-P	=2N2624: 32V, >16MHz, B>20	2a	Cen,Sty	ASY26, 2N1309
2N2627	Ge-P	NF/HF, 15V, 0,1A, 0,15W, >13MHz, B>15	2a	Cen,Sty	ASY26..27, 2N1309
2N2628	Ge-P	=2N2627: 24V, >15MHz, B>15	2a	Cen,Sty	ASY26..27, 2N1309
2N2629	Ge-P	=2N2627: 32V, >16MHz, B>20	2a	Cen,Sty	ASY26, 2N1309
2N262A	Si-P	=2N262: 30V	≈2e		BC213, BC258, BC308, BC558, ++
2N263	Si-N	Uni, 45V, 0,6A, 0,15W, B>45	5e	USA,TiX	BC167, BC182, BC237, BC547, ++
2N2630	Ge-P	S, 18V, 0,1A, 0,3W, >300MHz	2a	Ssi,Sty	—
2N2631	Si-N	VHF-A/Tr, 60V, 1,5A, PQ>3W(150MHz)	2a	USA,Rca,Tix	BFS23
2N2632	Si-N	S-L, 90/60V, 5A, 40W, >20MHz	49m	USA	2N5002, 2N5004, 2N5264..85
2N2633	Si-N	=2N2632: 120/60V	49m	USA	2N5284..85
2N2634	Si-N	=2N2632: 150/100V	49m	USA	2N5264..85
2N2635	Ge-P	S, 30V, 0,1A, 0,15W, >150MHz	2a	USA,Mot,Tix	2N2955..57
2N2639	Ge-P	S-L, 100V, 25A, 100W	23a	USA	2N1652..53, 2N2266..87
2N2637	Ge-P	S-L, 100V, 25A, 100W	23a	USA	2N1652..53, 2N2266..87
2N2639	Ge-P	S-L, 100V, 25A, 100W	23a	USA	2N1652..53, 2N2286..87
2N2639	Si-N	Dual, ra, 45V, 0,03A, 0,5W, >40MHz	TO-77	USA,EUR	BFY81, 2N2913..20
2N264	Si-N	=2N263: B>20	5e	USA,Tix	BC167, BC182, BC237, BC547, ++
2N2640	Si-N	Dual, ra, 45V, 0,03A, 0,5W, >40MHz	TO-77	USA,EUR	BFY81, 2N2913..20
2N2641	Si-N	Dual, ra, 45V, 0,03A, 0,5W, >40MHz	TO-77	USA,EUR	BFY81, 2N2913..20
2N2642	Si-N	Dual, ra, 45V, 0,03A, 0,5W, >40MHz	TO-77	USA,EUR	BFY81, 2N2913..20
2N2643	Si-N	Dual, ra, 45V, 0,03A, 0,5W, >40MHz	TO-77	USA,EUR	BFY81, 2N2913..20
2N2644	Si-N	Dual, ra, 45V, 0,03A, 0,5W, >40MHz	TO-77	USA,EUR	BFY81, 2N2913..20
2N2645	Si-N	Uni, 75V, 0,5A, 0,5W, >50MHz	2a	USA,Sgs	BC639, BCX24, 2N3700..01, 2SD667, ++
2N2646	UJT-P	Ip<5µA, Iv>4mA	5e	Gen, Mot, Phi	2N4871
2N2648	UJT-P			Tho,Tix	—
2N2646P	UJT-P	Ip<12µA, Iv>4mA	5e	Ssc	—
2N2647	UJT-P	=2N2646: Ip<2µA, Iv>6mA	5e		—
2N2648	Ge-P	NF/S, 30V, 1A, 0,3W, >10MHz	2a	Csr,Idi	—
2N2649	Si-N	NF/S, 65V, 1A, 0,7W, >100MHz	2a	Nsc	—
2N265	Ge-P	NF/S, 25V, 0,05A, 0,075W	1e	Csr,Etc	AC125..126, AC151, ASY26..27
2N2650	Si-N	=2N2649: 140V	2a	Nsc	—
2N2651	Si-N	S, 40V, 0,5A, 0,36W, >350MHz	2a	USA,Fch	BSS10, BSX26, BSX39, 2N3261
2N2652(A)	Si-N	Dual, 100V, 0,5A, 0,6W, >60MHz	TO-77	USA,Mot	BFX70..72, 2N2060, 2N2223
2N2654	Ge-P	VHF, 25V, 10mA, 0,1W, 250MHz	5g	Amp,Phc	AF109R, AF139, AF239(S)
2N2655	Si-N	NF/S, 100V, 0,5A, 15W(Tc=25°)	2a	Sca,Tra	BUX49, BUY41, 2SC1860
2N2658	Si-N	HF, 25V, 0,2A, 0,36W, >250MHz	2a	Trw	BC166, BC183, BC238, BC548, ++
2N2657	Si-N	NF/S, 60V, 5A, 4W(Tc=100°), >20MHz	2a	USA,Nsc,Tix	BFT32..34, 2N4895..97, 2N5336..39
2N2658	Si-N	=2N2657: 100V	2a	USA,Nsc,Tix	BFT33..34, 2N4895..97, 2N5339
2N2659	Ge-P	NF/S-L, 50V, 3A, 15W(Tc=25°)	2a	USA,Tix	2N1039
2N266	Ge-P	NF/S, 18V, 0,2A, 0,075W	1a	Gen	AC125..126, AC151, ASY26..27

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2N2660	Ge-P	=2N2659: 70V	2a	USA,Tix	2N1040
2N2661	Ge-P	=2N2659: 90V	2a	USA,Tix	2N1041
2N2662	Ge-P	NF/S-L, 50V, 3A, 15W(Tc=25°)	2a°	USA,Tix	2N2553, 2N2561
2N2663	Ge-P	=2N2662: 70V	2a°	USA,Tix	2N2554, 2N2562
2N2664	Ge-P	=2N2662: 90V	2a°	USA,Tix	2N2555, 2N2563
2N2665	Ge-P	NF/S-L, 50V, 3A, 15W(Tc=25°)	2a	USA,Tix	2N1039
2N2666	Ge-P	=2N2665: 70V	2a	USA,Tix	2N1040
2N2667	Ge-P	=2N2665: 90V	2a	USA,Tix	2N1041
2N2668	Ge-P	NF/S-L, 50V, 3A, 15W(Tc=25°)	2a°	USA,Tix	2N2553, 2N2561
2N2669	Ge-P	=2N2668: 70V	2a°	USA,Tix	2N2554, 2N2562
2N267	Ge-P	RF/IF AMP, 20V, 10mA, 0,08W, 400MHz	4g	Ray,Sty	AF124..127, AF200
2N2670	Ge-P	=2N2668: 90V	2a°	USA,Tix	2N2555, 2N2563
2N2671	Ge-P	VHF, 25V, 10mA, 0,1W, >200MHz	5g	Amp	AF108, AF109R, AF306
2N2672(A)	Ge-P	HF, 25..32V, 10mA, 0,1W, >18MHz	2a	Amp	AF124..127, AF200
2N2673	Si-N	Uni, 60V, 0,025A, 0,25W, 40MHz, B>8	2a	Gen	BC174, BC162, BC190, BC546, ++
2N2674	Si-N	=2N2673: B>12	2a	Gen	BC174, BC162, BC190, BC546, ++
2N2675	Si-N	=2N2673: B>22	2a	Gen	BC174, BC182, BC190, BC546, ++
2N2676	Si-N	=2N2673: B>45	2a	Gen	BC174, BC182, BC190, BC546, ++
2N2677	Si-N	=2N2673: 45V, B>20	2a	Gen	BC167, BC162, BC237, BC547, ++
2N2676	Si-N	=2N2673: 45V, B>45	2a	Gen	BC167, BC182, BC237, BC547, ++
2N2679	50Hz-Thy	30V, 0,35A(Tc=55°), Igt/Ih<0,02/<0,5mA	2a	USA,Mot,Tag	(2N2323A)
2N2679...A2686A	F-Thy	=2N2679..2686: <10µs	2a		—
2N268(A)	Ge-P	NF/S-L, 60V, 3A, 30W	23a	USA,Itt	AL102..103, AUY20, 2N2141, 2N2146, ++
2N2680	50Hz-Thy	=2N2679: 60V	2a		(2N2324A)
2N2661	50Hz-Thy	=2N2679: 100V	2a		(2N2324A)
2N2682	50Hz-Thy	=2N2679: 200V	2a		(2N2326A)
2N2663	50Hz-Thy	30V, 0,28A(Tc=55°), Igt/Ih<0,02/<1mA	2a	USA,Mot,Tag	(2N2323A)
2N2664	50Hz-Thy	=2N2663: 60V	2a		(2N2324A)
2N2685	50Hz-Thy	=2N2683: 100V	2a		(2N2324A)
2N2668	50Hz-Thy	=2N2683: 200V	2a		(2N2326A)
2N2667	50Hz-Thy	30V, 0,28A(Tc=55°), Igt/Ih<0,2/<2mA	2a	USA,Mot,Tag	N6605, TAG06Y, (2N2323, TAG615-100)
2N2668	50Hz-Thy	=2N2667: 60V	2a		2N6606, TAG06YY, (2N2324, TAG615-100)
2N2669	50Hz-Thy	=2N2667: 100V	2a		2N6607, TAG06A, (2N2324, TAG615-100)
2N269(A)	Ge-P	S, 20V, 0,1A, 0,12W, >4MHz	2a	Csr,Etc,Sty	ASY26..27, ASY48, ASY76..77
2N2690	50Hz-Thy	=2N2687: 200V	2a		2N6608, TAG06B, (2N2326, TAG615-200)
2N2691	Ge-P	NF/S-L, 100V, 20A, 100W	23a	USA	2N1652..53, 2N2286..87
2N2691A	Ge-P	=2N2691: 120V	23a		2N1653, 2N2287
2N2692	Si-N	Uni, 45V, 0,05, 0,3W, >42MHz, B>90	2a	USA,Tix	BC167, BC162, BC237, BC547, ++
2N2693+A12065	Si-N	=2N2692: B>60	2a	USA,Tix	BC167, BC182, BC237, BC547, ++
2N2694	Si-N	=2N2692: B>30	2a	USA,Tix	BC187, BC182, BC237, BC547, ++
2N2695	Si-P	NF/S, 25V, 0,5A, 0,36W, >100MHz	2a	USA,Sgs,Tix	BC327..328, BC636, 2N2906..07(A), ++
2N2696	Si-P	NF/S, 25V, 0,5A, 0,36W, >100MHz	2a	USA,Sgs,Tix	BC327..328, BC636, 2N2906..07(A), ++
2N2697	Si-N	NF/S-L, 80V, 5A, 10W(Tc=100°), >20MHz		Csr,Sem	(BDV10..12, 2SC3253)
2N2698	Si-N	=2N2697: 100V		Csr,Sem	(BDV10..12)
2N2699	Ge-P	S, 15V, 0,1A, 0,15W, >300MHz	2a	Phc	2N705A, 2N964(A), 2N2635, 2N2955..57
2N27	Ge-N	NF/HF, 20V, 0,3A, 0,05W, >1MHz	2a	Wes	(AC127, ASY28)
2N270	Ge-P	NF, 25V, 0,075A, 0,15W	1a	Csr,Etc	AC125..126, AC151, 2SB54, 2SB56
2N2706(MP)	Ge-P	NF-Tr, 32V, 0,2A, 0,28W	2a	Amp,Phc	AC128, AC152..153, 2SB324, 2SB415
2N2707	Ge-N/P	=2N2430+2N2706 pap	2a	Amp,Phc	AC127+AC128, AC127+AC152
2N2706	Si-N	VHF/UHF-M/O, >700MHz	5g	USA,Mot,Rca	BF377..378, BF669, BF763, 2N2657, ++
2N2709	Si-P	NF/S, 50V, 0,05A, 0,24W	2a	Ray,Sty	BC212, BC257, BC307, BC557, ++
2N271(A)	Ge-P	HF, 30V, 0,3A, 0,15W, 10MHz	2a	Csr,Etc	ASY26..27, 2N3323..25
2N2710	Si-N	S, 40V, 0,5A, 0,36W, <20/35ns	2a	USA,Mot	BSS10, BSX26, BSX39, 2N3261
2N2711	Si-N	Uni, 18V, 0,1A, 0,12W, B>30	7c	USA,Mic	BC166, BC193, BC236, BC546, ++
2N2713	Si-N	=2N2711: B>75	7c	USA,MIC	BC168, BC163, BC236, BC548, ++
2N2713	Si-N	Uni, 18V, 0,2A, 0,36W, 200MHz, B>30	7c	USA,Mic,Tho	BC168, BC163, BC236, BC548, ++
2N2714	Si-N	=2N2713: B>75	7c	USA,Mic,Tho	BC166, BC183, BC238, BC548, ++
2N2715	Si-N	Uni, 18V, 0,05A, 0,2W, B>30	7c	Gen,Sem	BC166, BC163, BC236, BC546, ++
2N2716	Si-N	=2N2715: B>75	7c	Gen,Sem	BC166, BC183, BC236, BC546, ++
2N2717	Ge-P	S, 25V, 15mA, 0,1W, >300MHz	2a	Idi,Ssi	(ASZ21, 2N2635, 2N2955..57)
2N2718	Ge-P	S, 20V, 0,4A, 0,24W, >150MHz	2a	USA	—
2N2719	Si-N	S, 25V, 0,2A, 0,3W, 200MHz	2a	Cen,Syl	BC238, BC548, BSY62, 2N706A, ++
2N272	Ge-P	NF, 30V, 0,5A, 0,15W	3a	Csr,Etc	AC125..126, AC151, 2SB54, 2SB56
2N2720	Si-N	Dual, 60V, 0,04A, 0,6W, >80MHz	TO-77	USA,Mot	BFX70..72, 2N2060, 2N2223
2N2721	Si-N	Dual, 80V, 0,04A, 0,6W, >80MHz	TO-77	USA,Mot	BFX70..72, 2N2060, 2N2223
2N2722	Si-N	Dual, ra, 45V, 0,04A, 0,6W, >100MHz	TO-77	USA,Mot,Nsc	BFY81, 2N2639..44, 2N2913..20

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2N2723	Si-N-Darl	Uni, 80V, 0,04A, 0,5W, B>2000	5	USA, Mot	—
2N2724	Si-N-Darl	=2723: B>7000	5	USA, Mot	—
2N2725	Si-N-Darl	=2723: 45V	5	USA, Mot	—
2N2726	Si-N	Vid/S, 200V, 0,5A, 1W, >15MHz, B>30	2a	USA	BSS48, 2N2440, 2SD413, 2SD576, 2SD624
2N2727	Si-N	=2N2726: B>75	2a	USA	BSS46, 2N2440, 2SD413, 2SD576, 2SD624
2N2728	Ge-P	S-L, 15V, 50A, 170W	38a	USA, Mot	2N4046..4053
2N2729	Si-N	HF/ZF, 30V, 0,05A, 0,3W, >800MHz	2a	USA	BF377..378, BF689, BF763, 2N2857, ++
2N273	Ge-P	NF, 32V, 0,5A, 0,15W	3a	Csr, Etc	AC125..126, AC151, 2SB54, 2SB56
2N2730	Ge-P	S-L, 80V, 65A, 170W	38a	Gpd, Sem	2N4050, 2N4053
2N2731	Ge-P	=2N2730: 60V	38a	Gpd, Sem	2N4049..4050, 2N4052..4053
2N2732	Ge-P	=2N2730: 40V	38a	Gpd, Sem	2N4048..4050, 2N4051..4053
2N2733	Ge-P	S-L, 60V, 65A, 170W	38a	Gpd, Sem	2N4050, 2N4053
2N2734	Ge-P	=2N2733: 60V	38a	Gpd, Sem	2N4049..4050, 2N4052..4053
2N2735	Ge-P	=2N2733: 40V	38a	Gpd, Sem	2N4048..4050, 2N4051..4053
2N2736	Ge-P	S-L, 80V, 65A, 170W	38a	Gpd, Sem	2N4050, 2N4053
2N2737	Ge-P	=2N2736: 80V	38a	Gpd, Sem	2N4049..4050, 2N4052..4053
2N2736	Ge-P	=2N2736: 40V	38a	Gpd, Sem	2N4048..4050, 2N4051..4053
2N2739	Si-N	S-L, 50V, 20A, 200W		Sem, Ssi, Stc	—
2N274	Ge-P	RF/IF AMP, 20V, 10mA, 0,08W, 400MHz	4g	Csr	AF124..127, AF200
2N2740	Si-N	=2N2739: 100V			—
2N2741	Si-N	=2N2739: 150V			—
2N2742	Si-N	=2N2739: 200V			—
2N2743	Si-N	=2N2739: 250V			—
2N2744	Si-N	=2N2739: 300V			—
2N2745	Si-N	S-L, 50V, 20A, 200W		Sem, Ssi, Stc	—
2N2746	Si-N	=2N2745: 100V			—
2N2747	Si-N	=2N2745: 150V			—
2N2748	Si-N	=2N2745: 200V			—
2N2749	Si-N	=2N2745: 250V			—
2N2750	Si-N	=2N2745: 300V			—
2N2751	Si-N	S-L, 50V, 20A, 200W		Sem, Ssi, Stc	—
2N2752	Si-N	=2N2751: 100V			—
2N2753	Si-N	=2N2751: 150V			—
2N2754	Si-N	=2N2751: 200V			—
2N2755	Si-N	=2N2751: 250V			—
2N2756	Si-N	=2N2751: 300V			—
2N2757	Si-N	S-L, 50V, 30A, 200W	49m	USA, Whs	2N6324..25
2N2756	Si-N	=2N2757: 100V	49m		2N6324..25
2N2759	Si-N	=2N2757: 150V	49m		2N6324..25
2N2760	Si-N	=2N2757: 200V	49m		2N6324..25
2N2761	Si-N	=2N2757: 250V	49m		2N6324..25
2N2762	Si-N	=2N2757: 300V	49m		2N6324..25
2N2763	Si-N	S-L, 50V, 30A, 200W	49m	USA, Whs	2N6324..25
2N2764	Si-N	=2N2763: 100V	49m		2N6324..25
2N2765	Si-N	=2N2763: 150V	49m		2N6324..25
2N2766	Si-N	=2N2763: 200V	49m		2N6324..25
2N2767	Si-N	=2N2763: 250V	49m		2N6324..25
2N2768	Si-N	=2N2763: 300V	49m		2N6324..25
2N2769	Si-N	S-L, 50V, 30A, 200W	49m	USA, Whs	2N6324..25
2N277	Ge-P	NF/S-L, 40V, 15A, 170W	38a	USA, Mot	2N1980..82, 2N2075..82, 2N2491, ++
2N2770	Si-N	=2N2769: 100V	49m		2N6324..25
2N2771	Si-N	=2N2769: 150V	49m		2N6324..25
2N2772	Si-N	=2N2769: 200V	49m		2N6324..25
2N2773	Si-N	=2N2769: 250V	49m		2N6324..25
2N2774	Si-N	=2N2769: 300V	49m		2N6324..25
2N2775	Si-N	S-L, 50V, 30A, 200W	49m	USAWhs	2N6324..25
2N2776	Si-N	=2N2775: 100V	49m		2N6324..25
2N2777	Si-N	=2N2775: 150V	49m		2N6324..25
2N2778	Si-N	=2N2775: 200V	49m		2N6324..25
2N2779	Si-N	=2N2775: 250V	49m		2N6324..25
2N278	Ge-P	=2N277: 50V	38a	USA, Mot	2N1980..82, 2N2075..77, 2N2491, ++
2N2780	Si-N	=2N2775: 300V	49m		2N6324..25
2N2781	Si-N	HF/S-L, 75V, 2A, 15W, >140MHz	2a	USA	—
2N2762	Si-N	HF/S-L, 100V, 2A, 15W, >140MHz	2a	USA	—
2N2783	Si-N	HF/S-L, 100V, 2A, 15W, >140MHz	2a	USA	—
2N2764	Si-N	SS, 15V, 0,3W, <9/9ns	2a	USA	—

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2N2785	Si-N-Darl	Uni, 60V, 0,2A, 0,5W, B>2000	5	Gen, Mot, Ray	BFX67, 2N999
2N2786(A)	Ge-P	HF, 35V, 0,15A, >225MHz	2a	Amp, Sca, Spe	—
2N2787	Si-N	Uni, 75V, 0,8A, 0,8W, 300MHz, B>20	2a	USA	BC140..141, BSW39, 2N2218..19A, ++
2N2788	Si-N	=2N2787: B>40	2a	USA	BC140..141, BSW39, 2N2218..19A, ++
2N2789(S)	Si-N	=2N2787: B>100	2a	USA	BC140..141, BSW39, 2N2218..19A, ++
2N279	Ge-P	NF, -/20V, 0,05A, 0,125W, β>20	1a	Csr, Etc	AC125..126, AC151, 2SB54, 2SB56
2N2790	Si-N	=2N2787: 0,5W	2a	USA	BC639, BSW63..64, 2N2221..22A, ++
2N2791	Si-N	=2N2787: 0,5W, B>40	2a	USA	BC639, BSW63..64, 2N2221..22A, ++
2N2792	Si-N	=2N2787: 0,5W, B>100	2a	USA	BC639, BSW63..64, 2N2221..22A, ++
2N2793	Ge-P	S-L, 75V, 60A, 170W	38a	Cen	2N4050, 2N4053
2N2794	P-FET	Uni, 20V, Idss>1,5mA	2a	old	2N2497..98, 2N2500
2N2795	Ge-P	S, 25V, 0,1A, 0,075W, 450MHz	2a	Idi	(2N2635, 2N2955..57)
2N2798	Ge-P	S, 25V, 0,1A, 0,075W, 450MHz	2a	Idi	(2N2635, 2N2955..57)
2N2797	Ge-P	S, 40V, 0,1A, 0,075W, >150MHz	2a	Spr	(2N2955..57)
2N2798	Ge-P	S, 60V, 0,1A, 0,075W, >120MHz	2a	Spr	—
2N2799	Ge-P	S, 30V, 0,1A, 0,075W, >120MHz	2a	Spr	(2N2635, 2N2955..57)
2N28	Ge-N	NF/HF, 20V, 0,3A, 0,12W	2a	Wes	(AC127, ASY28)
2N260	Ge-P	=2N279: β>47	1a	Csr, Etc	AC125..128, AC151, 2SB54, 2SB56
2N2800(S)	Si-P	S, 50V, 0,8A, 0,8W, 34/130ns, B>30	2a	USA, Mot	BSW40, 2N2904..05(A), 2N3468, 2SA717, ++
2N2801(S)	Si-P	=2N2800: B>75	2a	USA, Mot	BSW40, 2N2904..05(A), 2N3468, 2SA717, ++
2N2602	Si-P	Dual, ra, 25V, 0,03A, 0,5W, >60MHz	TO-77	Mot, Tix, ++	BFX36, 2N3806..11, 2N4015..16
2N2803	Si-P	Dual, ra, 25V, 0,03A, 0,5W, >60MHz	TO-77	Mot, Tix, ++	BFX36, 2N3806..11, 2N4015..16
2N2804	Si-P	Dual, ra, 25V, 0,03A, 0,5W, >60MHz	TO-77	Mot, Tix, ++	BFX36, 2N3606..11, 2N4015..16
2N2805	Si-P	Dual, ra, 25V, 0,03A, 0,5W, >60MHz	TO-77	Mot, Tix, ++	BFX36, 2N3606..11, 2N4015..16
2N2806	Si-P	Dual, ra, 25V, 0,03A, 0,5W, >60MHz	TO-77	Mot, Tix, ++	BFX36, 2N3906..11, 2N4015..16
2N2807	Si-P	Dual, ra, 25V, 0,03A, 0,5W, >60MHz	TO-77	Mot, Tix, ++	BFX36, 2N3606..11, 2N4015..16
2N2806	Si-N	UHF, 30V, 0,025A, 0,2W, >1GHz	5g	Ray	BF377..378, BF689, BF763, 2N2857, ++
2N2608A	Si-N	=2N2806: >1,5GHz	5g		BF377..378, BF689, BF763, 2N2857, ++
2N2809	Si-N	UHF, 30V, 0,025A, 0,2W, >1GHz	5g	Ray	BF377..378, BF689, BF763, 2N2857, ++
2N2809A	Si-N	=2N2809: >1,3GHz	5g		BF377..378, BF689, BF763, 2N2657, ++
2N281	Ge-P	NF, 16V, 0,125A, 0,125W	1a	Csr, Etc	AC125..126, AC151, 2SB54, 2SB56
2N2810	Si-N	UHF, 24V, 0,025A, 0,2W, >1GHz	5g	Ray	BF377..378, BF689, BF763, 2N2857, ++
2N2810A	Si-N	=2N2810: >1,3GHz	5g		BF377..378, BF689, BF763, 2N2857, ++
2N2811	Si-N	S-L, 80V, 10A, 70W, >15MHz, B>20	49m	USA	2N5268..89, 2N5542
2N2812	Si-N	=2N2811: B>40	49m	USA	2N5268..89, 2N5542
2N2813	Si-N	=2N2811: 120V	49m	USA	2N5268..89, 2N5542
2N2814	Si-N	=2N2811: 120V, B>40	49m	USA	2N5288..89, 2N5542
2N2815	Si-N	S-L, 80V, 20A, 200W	49m	USA, Tho	2N6324..25
2N2816	Si-N	=2N2815: 100V	49m		2N6324..25
2N2817	Si-N	=2N2815: 150V	49m		2N6324..25
2N2818	Si-N	=2N2815: 200V	49m		2N6324..25
2N2819	Si-N	S-L, 80V, 25A, 200W	49m	USA, Tho	2N6324..25
2N282	Ge-P	=2x2N281: gep	1a	Csr, Etc	AC125..126, AC151, 2SB54, 2SB56
2N2820	Si-N	=2N2819: 100V	49m		2N6324..25
2N2821	Si-N	=2N2819: 150V	49m		2N6324..25
2N2822	Si-N	=2N2819: 200V	49m		2N6324..25
2N2823	Si-N	S-L, 80V, 30A, 200W	49m	USA, Tho	2N6324..25
2N2824	Si-N	=2N2823: 100V	49m		2N6324..25
2N2825	Si-N	=2N2823: 150V	49m		2N6324..25
2N2826	Ge-P	NF-L, -/15V, 1A, 7,5W	43m	Gpd, Sem	(AD182)
2N2827	Ge-P	NF-L, 40V, 1,5A, 7,5W	43m	Del	—
2N2828	Si-N	S-L, 60V, 3A, 40W	43m	USA	2N5002, 2N5004, 2N5284..85
2N2829	Si-N	S-L, 80V, 3A, 40W	43m	USA	2N5002, 2N5004, 2N5284..85
2N283	Ge-P	NF/S, 20V, 0,01A, 0,125W	1a	Csr, Etc	AC125..126, AC151, 2SB54, 2SB56
2N2831	Si-N	HF, 40V, 0,2A, 0,36W, >250MHz	2a	Trw	BC547, BFX94..95, 2N2221..22(A), ++
2N2832	Ge-P	NF/S-L, 80V, 20A, 85W	23a	USA, Mot	2N1652..53, 2N2286..87
2N2833	Ge-P	=2N2832: 120V	23a	USA, Mot	2N1653, 2N2287
2N2834	Ge-P	=2N2832: 140V	23a	USA, Mot	—
2N2835	Ge-P	NF-L, 32V, 1A, 16W(Tc=50°)	22a	Gpd, Phc	(AD162)
2N2836	Ge-P	NF-L, 55V, 3,5A, 37W	23a	Gpd, Phc	AD149, AUY19..20, 2N1545..48, ++
2N2837	Si-P	=2N2800: 0,5W	2a	USA, Mot	2N2906..07(A), 2N4026..29
2N2836	Si-P	=2N2801: 0,5W	2a	USA, Mot	2N2906..07(A), 2N4026..29
2N284	Ge-P	NF/S, 32V, 0,125A, 0,125W	1a	Csr, Etc	AC125..126, AC151, 2SB54, 2SB56
2N2840	UJT-P	Ip<10µA, Iv>0,24mA	5e	Gen	—
2N2841	P-FET	Uni, 30V, Idss>0,025mA, Up<1,7V	2a	USA, Isi	2N5471..72
2N2842	P-FET	Uni, 30V, Idss>0,065mA, Up<1,7V	2a	USA, Isi	2N5472..73

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2N2843	P-FET	Uni, 30V, Idss>0,2mA, Up<1,7V	2a	USA,Isi	2N5265
2N2844	P-FET	Uni, 30V, Idss>0,44mA, Up<1,7V	2a	USA,Isi	2N5020, 2N5266..67
2N2845	Si-N	S, 60V, 0,5A, 0,36W, <40/40ns, B>30	2a	Mot,Sgs,Tix	2N4014
2N2846	Si-N	=2N2845: 0,6W	2a	Mot,Sgs,Tix	BSS27, BSV77, BSV95, 2N5189, ++
2N2847	Si-N	=2N2845: B>40	2a	Mot,Sgs,Tix	2N4014
2N2848	Si-N	=2N2845: 0,8W, B>40	2a	Mot,Sgs,Tix	BSS27, BSV77, BSV95, 2N5189, ++
2NA122212849(-1)	Si-N	NF/S, 100V, 3A, 0,85W, B>100	2a	USA	BSX64, 2N4239, 2SC696, 2SC2214
2N2849-2..2856-2	Si-N	=2N2849(-1)..2N2856(-1):	49m		2N5002, 2N5004, 2N5284..85
2N2849-3..2856-3	Si-N	=2N2849(-1)..2N2656(-1):	≈49m		(BD241C, BD539C, BD937, 2SD712, ++)
2N284A	Ge-P	=2N284: 60V	1a		ASY48, ASY77
2N285(A,B)	Ge-P	NF/S-L, -/40V, 3A, 25W(Tc=45°)	23a	USA	AD149, AUY19..20, 2N2143..46, ++
2N2850(-1)	Si-N	=2N2849: B>40	2a	USA	BSX64, 2N4239, 2SC696, 2SC2214
2N2851(-1)	Si-N	=2N2849: B>40	2a	USA	BSX64, 2N4239, 2SC696, 2SC2214
2N2852(-1)	Si-N	=2N2849: B>20	2a	USA	BSX64, 2N4239, 2SC696, 2SC2214
2N2853(-1)	Si-N	NF/S, 60V, 3A, 0,85W, B>40	2a	USA	BSX62..64, 2N4238..39, 2SC696, 2SC2214
2N2854(-1)	Si-N	=2N2853: B>100	2a	USA	BSX62..64, 2N4238..39, 2SC696, 2SC2214
2N2855(-1)	Si-N	=2N2853: B>40	2a	USA	BSX62..64, 2N4238..39, 2SC696, 2SC2214
2N2856(-1)	Si-N	=2N2853: B>20	2a	USA	BSX62..64, 2N4238..39, 2SC696, 2SC2214
2N2857	Si-N	UHF-V/M/O, ra, 30V, 0,04A, 0,2W, >1GHz	5g	USA,EUR,Mic	BF377..378, BF689, BF763, BFX63
2N2858	Si-N	NF/S, 100V, 3A, 0,6W	2a	USA	BSX64, 2N4239, 2SC696(A), 2SC2214
2N2859	Si-N	=2N2858: 120V	2a	USA	2SC696A
2N2860	Ge-P	S, 18V, 0,15A, 0,15W, >250MHz	2a	Syl	2N2635, 2N2955..57
2N2861	Si-P	Uni, ra, 25V, 0,1A, 0,3W, >60MHz, B>50	2a	USA,Tix	BC214, BC259, BC309, BC559, ++
2N2862	Si-P	=2N2861: >45MHz, B>25	2a	USA,Tix	BC214, BC259, BC309, BC559, ++
2N2863	Si-N	VHF-O/Tr, 60V, 1A, 0,8W, 250MHz	2a	Idi,Tix	BFS23, 2SC2419
2N2864	Si-N	VHF-O/Tr, 60V, 1A, 0,8W, 250MHz	2a	Idl,Tix	BFS23, 2SC2419
2N2865	Si-N	VHF/UHF-O/Tr, 25V, 0,05A, >600MHz	5g	USA,Tix	BFR37, BFW30, BFX59, BFX73
2N2866	Si-N	NF/S-L, 120V, 2A, 40W, B>20	≈49	USA	2N5284..85
2N2867	Si-N	=2N2868: B>40	≈49	USA	2N5284..85
2N2868	Si-N	Uni, 60V, 1A, 0,8W, >50MHz	2a	USA,Sgs	BC140..141, BC300..302, 2N1990, ++
2N2869	Ge-P	NF-L, 60V, 10A, 30W	23a	USA,Rca	AL100..101, AUY21, 2N2292..93, ++
2N2870	Ge-P	=2N2869: 60V	23a	USA,Rca	AL100..101, AUY37, 2N2292..93, ++
2N2871	Si-P	Dual, Chopper, 60V, 0,2A(ss), 0,4W	TO-77	Hug	—
2N2872	Si-P	=2N2871: 110V	TO-77	Hug	—
2N2873	Ge-P	HF, 35V, 10mA, 0,115W, >300MHz	5g	Rca,Sty	AF109R, AF139, AF239(S)
2N2874	Si-N	NF/HF-L, 75V, 2A, 15W, >140MHz	2a	Sca,SSi,Trw	(BD139, BD230, BD519, BD527, ++)
2N2875	Si-P	NF/S-L, 60V, 2A, 20W, >25MHz	≈49	Sem,SSi,Tra	2N5003, 2N5005, 2N5286..87
2N2876	Si-N	VHF-L, 60V, 2,5A, PQ>3W(150MHz)	49a	Rca,Sem	BLY35, 2N3632
2N2877	Si-N	S-L, 60V, 5A, 30W(Tc=100°), >30MHz, B>20	≈49	USA,Tix	2N5002, 2N5004, 2N5284..85
2N2878	Si-N	=2N2877: >50MHz, B>40	≈49	USA,Tix	2N5002, 2N5004, 2N5284..85
2N2879	Si-N	=2N2877: 100V	≈49	USA,Tix	2N5002, 2N5004, 2N5284..85
2N2880	Si-N	=2N2877: 100V, >50MHz, B>40	≈49	USA,Tix	2N5002, 2N5004, 2N5284..85
2N2881	Si-P	NF/S, 60V, 2A, 8,5W(Tc=25°)	2a	USA	BSS17..18, 2N4235..36, 2N5322..23
2N2882	Si-P	=2N2881: 100V	2a	USA	BSS17..18, 2N4235..36, 2N5322..23
2N2883	Si-N	VHF/UHF-O/Tr, 40V, 0,3A, PQ>0,5W(500MHz)	2a	USA,Tix	BFS50, MRF515, MRF629, 2N3948
2N2884	Si-N	=2N2883: PO>0,75W(500MHz)	2a	USA,Tix	BFS50, MRF515, MRF629, 2N3948
2N2885	Si-N	S, 40V, 0,15W, >300MHz, <40/-ns	24b	Tra	BSS10..11, BSX19..20, 2N2368..89(A), ++
2N2886	Si-N	NF/S, 50V, 0,5A, 0,8W	2a	Trw	BC140..141, BC300..302, 2N3053, ++
2N2887	Si-N	HF-L, 100V, 1,2A, 25W, >140MHz	49a	USA	—
2N2888	50Hz-Thy	200V, 16A(Tc=65°), Igt/<40mA	21b	USA,Tag	2N685, T12N200, MCR3935-4, C35B, ++
2N2889	50Hz-Thy	=2N2888: 250V	21b		2N686, T12N300, MCR3935-5, C35H, ++
2N2890	Si-N	NF/S, 100V, 2A, 0,8W, >30MHz, B>30	2a	USA,Nsc,Tho	BSX64, 2N4239, 2SC696(A), 2SC2214
2N2891	Si-N	=2N2890: B>50	2a	USA,Nsc,Tho	BSX64, 2N4239, 2SC696(A), 2SC2214
2N2892	Si-N	S-L, 100V, 5A, 30W, >30MHz, B>30	49m	USA,Tix	2N5002, 2N5004, 2N5284..85
2N2893	Si-N	=2N2892: B>50	49m	USA,Tix	2N5002, 2N5004, 2N5284..85
2N2894(A)	Si-P	S, 12V, 0,2A, 0,36W, 23/34ns	2a	USA,EUR	BFX36
2N2895	Si-N	Uni, 120V, 1A, 0,5W, >120MHz	2a	USA,Mot,Rca	BCX22, 2N3700..01, 2SC2235, 2SD667, ++
2N2896	Si-N	Uni, 140V, 1A, 0,5W, >120MHz	2a	USA,Mot,Rca	2N3700..01, 2SC2383, 2SC3228
2N2897	Si-N	Uni, 60V, 1A, 0,5W, >120MHz	2a	USA,MOt,Rca	BC337A, BC637, BC639, 2SD667, ++
2N2898	Si-N	=2N2895	2a	USA,Mot,Rca	→2N2895
2N2899	Si-N	=2N2896	2a	USA,Mot,Rca	→2N2896
2N29	Ge-N	NF/HF, 20V, 0,3A, 0,12W	2a	Wes	(AC127, ASY28)
2N290	Ge-P	S-L, 70V, 12A, 55W	38a	Del	2N1961..62, 2N2079..80, 2N2490, ++
2N2900	Si-N	=2N2897	2a	USA,Mot,Rca	→2N2897
2N2902	Si-N	S-L, 120V, 0,75A, 40W		Tix	—
2N2903(A)	Si-N	Dual, 60V, 0,05A, 0,3W, >60MHz	TO-77	USA,Mot,Sgs	BFY81, 2N2639..44, 2N2913..20

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2N2904(S)	Si-P	Uni, 60/40V, 0,6A, 0,8W, >200MHz, B>40	2a	USA,EUR,Mic	BSW40, 2N4030..33, 2N4036..37
2N2904A(AS)	Si-P	=2N2904: 60/60V	2a		BSW40, 2N4030..33, 2N4036..37
2N2905(A,S)	Si-P	=2N2904: B>100	2a	USA,EUR,Mic	BSW40, 2N4030..33, 2N4036..37
2N2906(A)	Si-P	=2N2904: 0,4W	2a	USA,EUR,Mic	2N4026..29
2N2907(A)	Si-P	=2N2904: 0,4W, B>100	2a	USA,EUR,Mic	2N4026..29
2N2908	Si-N	S-L, 80V, 5A, 45W		Sty	2N1722..23,(BD243B, BD539B, BD951++)
2N2908	Si-N	Uni, 80V, 1A, 0,4W, >50MHz	2a	Sca,SSI	BC337A, BC637, BC639, 2SD667, ++
2N291	Ge-P	NF, 30V, 0,5A, 0,16W	3a	Csr,Etc	AC125..126, AC151, 2SB54, 2SB56
2N2910	Si-N	Dual, 45V, 0,3W, >55MHz	TO-77	Gen,SSi,++	BFX70..72, 2N2060, 2N2223, 2N3408..11
2N2911	Si-N	S, 150V, 3A, 5W(Tc=25°)	2a	USA	BUX49, BUY41
2N2912	Ge-P	S-L, 15V, 25A, 75W(Tc=35°)	2a	Gpd,Mot	—
2N2913	Si-N	Dual, ra, 45V, 0,03A, >60MHz	TO-77	USA,Mot,Nsc	BFY61, 2N2639..44
2N2913	Si-N			Sgs,Tix,++	—
2N2914	Si-N	Dual, ra, 45V, 0,03A, >60MHz	TO-77		BFY61, 2N2639..44
2N2915(A)	Si-N	Dual, ra, 45V, 0,03A, >60MHz	TO-77		BFY61, 2N2639..44
2N2916(A)	Si-N	Dual, ra, 45V, 0,03A, >60MHz	TO-77		BFY61, 2N2639..44
2N2917	Si-N	Dual, ra, 45V, 0,03A, >60MHz	TO-77		BFY61, 2N2639..44
2N291S	Si-N	Dual, ra, 45V, 0,03A, >60MHz	TO-77		BFY61, 2N2639..44
2N2919(A)	Si-N	Dual, ra, 45V, 0,03A, >60MHz	TO-77		BFY61, 2N2639..44
2N292	Ge-N	HF, 30V, 0,3A, 0,085W, 5MHz	2a	Csr,Etc,Sam	—
2N2920(A)	Si-N	Dual, ra, 45V, 0,03A, >60MHz	TO-77		BFY61, 2N2639..44
2N2921	Si-N	Uni, 25V, 0,1A, 0,2W, 300MHz, β>35	7c	Sem,Tho	BC168, BC163, BC238, BC548, ++
2N2922	Si-N	=2N2921: β>55	7c	Sam,Tho	BC168, BC163, BC238, BC546, ++
2N2923	Si-N	=2N2921: β>90	7c	Gen,Tho,++	BC168, BC183, BC238, BC548, ++
2N2924	Si-N	=2N2921: β>150	7c	Gen,Tho,++	BC168, BC183, BC238, BC548, ++
2N2925	Si-N	=2N2921: β>235	7c	Gen,Tho,++	BC168, BC183, BC238, BC548, ++
2N2926	Si-N	=2N2921: β>35	7c	Gen,Tho,++	BC168, BC183, BC238, BC548, ++
2N2927	Si-P	S, 25V, 0,5A, 0,6W, <75/170ns	2a	USASgs	2N3467..68, 2SA717, 2SA742
2N2928	Ge-P	HF, 15V, 0,1A, 0,15W, >400MHz	5g	Syl	2N3283..86, (AF139, AF239(S))
2N2929	Ge-P	VHF-O/Tr, 25V, 0,1A, 0,3W, 1100MHz	2a	Idi,Mot	—
2N292A	Ge-N	=2N292: 0,1W	2a		—
2N293	Ge-N	HF, 30V, 0,3A, 0,085W, 8MHz	2a	Csr,Etc,Sam	—
2N2930	Ge-P	NF/S, 30V, 0,5A, 0,25W, >4MHz	2a	USA	ASY76..77
2N2931	Si-N	Min, NF, 5V, 0,05A, 0,05W, >20MHz, β>30	≈36c	Itt	BC121..123
2N2932	Si-N	=2N2931: β>70	≈36c	Itt	BC121..123
2N2933	Si-N	=2N2931: β>45	≈36c	Itt	BC121..123
2N2934	Si-N	=2N2931: 45V	≈36c	Itt	BC123
2N2935	Si-N	=2N2931: 45V, β>70	≈36c	Itt	BC123
2N2938	Si-N	Dual, 80V, 0,03A, 0,6W, >30MHz	TO-77	Ray,Sem,Sty	BFY81, 2N2639..44, 2N2919..20
2N2937	Si-N	Dual, 60V, 0,03A, 0,6W, >30MHz	TO-77	Ray,Sem,Sty	BFY61, 2N2639..44, 2N2919..20
2N2938	Si-N	S, 25V, 0,5A, 0,3W, >500MHz, <30/30ns	2a	Etc,Far	BSS10, BSX26, BSX26, BSX39, 2N3261
2N2939	Si-N	NF/S, 75V, 1A, 0,8W, >150MHz	2a	Etc,SSi,Tra	BC140..141, BSX45..47, 2N1990, ++
2N2940	Si-N	=2N2939: 120V	2a	Etc,SSi,Tra	BSS42, BSW67, BSX47, 2N2405, ++
2N2941	Si-N	=2N2939: 150V	2a	Etc,SSi,Tra	BSS43, BSW68
2N2942	Ge-P	S, 50V, 0,1A, 0,15W, >150MHz	2a	Spr	—
2N2943	Ge-P	=2N2942: 30V, >120MHz	2a	Spr	2N2635, 2N2955..57
2N2944(A)	Si-P	Chopper, 15V, 0,1A, 0,4W, 15MHz	2a	Mot,Tix,++	2N5229
2N2945(A)	Si-P	Chopper, 25V, 0,1A, 0,4W, 13MHz	2a	Mot,Tix,++	2N5230
2N2946(A)	Si-P	Chopper, 25V, 0,1A, 0,4W, 12MHz	2a	Mot,Tix,++	2N5231
2N2947	Si-N	HF-L, 80V, 1,5A, PQ=15W(50MHz)	23a	Mot,Sca,SSi	—
2N2946	Si-N	HF-L, 40V, 1,5A, PQ=15W(30MHz)	23a	Mot,Sca,SSi	—
2N2949	Si-N	HF-Tr/E, 80V, 0,7A, PQ=3,5W(50MHz)	2a	Mot,Sca,SSi	—
2N2950	Si-N	HF-Tr/E, 80V, 0,7A, PQ=3,5W(50MHz)	49a	Mot,Sca,SSi	—
2N2951(S)	Si-N	HF-A/Tr, 80V, 0,25A, PQ=0,6W(50MHz)	2a	Mot,Tix,++	BFX55, MRF229..230
2N2952	Si-N	HF-A/Tr, 80V, 0,25A, PQ=0,6W(50MHz)	2a	Mot,Tix,++	(BFX55, MRF229..230)
2N2953	Ge-P	NF/S 30V, 0,15A, 0,12W, 10MHz	2a	Can,Spe,Sty	AC125..128, AC151, ASY28, ASY76..77
2N2954	Si-N	HF-O/Tr, 30V, 0,5A, 0,2W, >300MHz		Phc	BFS51, BFQ42, BFR98, BFX55, ++
2N2955	Ge-P	S, 40V, 0,1A, 0,15W, 32/53ns	2a	Idi,Mot,SSi	—
2N2956	Ge-P	S, 40V, 0,1A, 0,15W, 25/55ns	2a	Idi,Mot,SSi	—
2N2957	Ge-P	S, 40V, 0,1A, 0,15W, 22/50ns	2a	Idi,Mot,SSi	—
2N2956(S)	Si-N	S, 80V, 0,6A, 0,6W, <95/500ns, B>40	2a	Mot,Sgs,++	BSW27..26, BSW51..54, 2N221S..19(A),++
2N2959(S)	Si-N	=2N2956: B>100	2a	Mot,Sgs,++	BSW27..26, BSW51..54, 2N2216..19(A),++
2N296	Ge-P	NF/S-L, -/60V, 2A, 20W	23a	USA	AL102..103, AUY19..20, 2N2145..48,++
2N2960	Si-N	S, 80V, 0,6A, 0,6W, <95/500ns	2a	Ray,Sem,Tra	BSW27..26, BSW51..54, 2N2216..19(A),++
2N2961	Si-N	S, 80V, 0,6A, 0,6W, <95/500ns	2a	Ray,Sam,Tra	BSW27..26, BSW51..54, 2N2216..19(A),++
2N2962	Ge-P	VHF-A/Tr, 40V, 0,3A, 0,35W, >560MHz	≈49m	Sca,Spr	—

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2N2963	Ge-P	VHF-A/Tr, 40V, 0,3A, 0,35W, >560MHz	≈49m	Sca,Spr	—
2N2964	Ge-P	VHF-A/Tr, 30V, 0,3A, 0,35W, >560MHz	≈49m	Sca,Spr	—
2N2965	Ge-P	VHF-A/Tr, 30V, 0,3A, 0,35W, >560MHz	≈49m	Sca,Spr	—
2N2966	Ge-P	VHF, 20V, 0,1A, 0,06W, >500MHz		Phc	2N3283..86, (AF139, AF239(S))
2N2967	Si-N	SS, 12V, 0,3W, <15/15ns	2a	Phc	BSS 11..12, BSY 17..18, 2N2368..69(A),++
2N2968	Si-P	Chopper, 30V, 0,05A, 0,15W, >10MHz	2a	USA	2N2946
2N2969	Si-P	Chopper, 30V, 0,05A, 0,15W, >10MHz	2a	USA	2N2946
2N297(A)	Ge-P	NF/S-L, 60V, 4A, 85W	23a	USA, Mot	AL 102..103, AUY 21..22, 2N1545..48,++
2N2970	Si-P	Chopper, 20V, 0,05A, 0,15W, >8MHz	2a	USA	2N2946
2N2971	Si-P	Chopper, 20V, 0,05A, 0,15W, >8MHz	2a	USA	2N2946
2N2972	Si-N	=2N2913: 0,3W	TO-71	USA,Mot,Sgs	BFW51..52
2N2973	Si-N	=2N2914: 0,3W	TO-71	USA,Mot,Sgs	BFW51..52
2N2974	Si-N	=2N2915: 0,3W	TO-71	USA,Mot,Sgs	BFW51..52
2N2975	Si-N	=2N2916: 0,3W	TO-71	USA,Mot,Sgs	BFW51..52
2N2976	Si-N	=2N2917: 0,3W	TO-71	USA,Mot,Sgs	BFW51..52
2N2977	Si-N	=2N2918: 0,3W	TO-71	USA,Mot,Sgs	BFW51..52
2N2978	Si-N	=2N2919: 0,3W	TO-71	USA,Mot,Sgs	BFW51..52
2N2979	Si-N	=2N2920: 0,3W	TO-71	USA,Mot,Sgs	BFW51..52
2N2980	Si-N	Dual, 100V, 0,5A, 0,25W, >60MHz	TO-71	USA,Mic,Sgs	(BFX70..72, 2N2060, 2N2223)
2N2961	Si-N	Dual, 100V, 0,5A, 0,25W, >50MHz	TO-71	USA,Mic,Sgs	(BFX70..72, 2N2060, 2N2223)
2N2982	Si-N	Dual, 100V, 0,5A, 0,25W, >50MHz	TO-71	USA,Mic,Sgs	(BFX70..72, 2N2060, 2N2223)
2N2963	Si-N	NF/S, 155V, 3A, 1W, 60MHz, B>20	2a	USA	BUX49..53, BUY41, 2SD625
2N2964	Si-N	=2N2983: 185V	2a	USA	BUX50..53, 2SD625
2N2985	Si-N	=2N2963: B>40	2a	USA	BUX49..53, BUY41, 2SD625
2N2986	Si-N	=2N2963: 185V, B>40	2a	USA	BUX50..53, 2SD625
2N2967	Si-N	NF/S, 95V, 1A, 15W(Tc=100°), B>25	2a	USA,Tix	BUX49..53, BUY41, 2SD625
2N2968	Si-N	=2N2987: 155V	2a	USA,Tix	BUX49..53, 2SD625
2N2989	Si-N	=2N2987: B>60	2a	USA,Tix	BUX49..53, BUY41, 2SD625
2N299	Ge-P	HF, 5V, 5mA, 0,02W, 110MHz	2a	Phc	AF106, AF109R, AF124..125, AF200
2N2990	Si-N	=2N2967: 155V, B>60	2a	USA,Tix	BUX49..53, 2SD625
2N2991	Si-N	=2N2987:	49m	USA,Tix	(2SC2275(A), 2SC2529..29, 2SD608,++)
2N2992	Si-N	=2N2988:	49m	USA,Tix	(2SC2275A, 2SC2529, 2SD608, 2SD759,++)
2N2993	Si-N	=2N2969:	49m	USA,Tix	(2SC2275(A), 2SC2528..29, 2SD608,++)
2N2994	Si-N	=2N2990:	49m	USA,Tix	(2SC2275A, 2SC2529, 2SD608, 2SD759,++)
2N2995	Si-N	NF/S, 120V, 1A, >10MHz	49m	USA	(2SC2275(A), 2SC2528..29, 2SD608,++)
2N2996	Ge-P	UHF, 15V, 0,05A, 0,075W, >400MHz	5g	SSi,Sty,Tix	AF139, AF239(S), 2N3283..86
2N2997	Ge-P	UHF, 30V, 0,05A, 0,075W, >400MHz	5g	SSi,Sty,Tix	AF139, AF239(S), 2N3263..86
2N2998	Ge-P	UHF, 15V, 0,05A, 0,075W, >600MHz	5g	Sty,Tix	AF139, AF239(S), 2N3283..86
2N2999	Ge-P	UHF, 15V, 0,05A, 0,075W, >1400MHz	5g	Sty,Tix	—
2N30	Ge-P	NF/HF, 30V, 7mA, 0,1W		Gen	AF124..127, AF200
2N300	Ge-P	HF, 5V, 5mA, 0,02W, 95MHz	2a	Phc	AF106, AF109R, AF124..125, AF200
2N3000	Ge-P	NF, 45V, 0,4A, 0,15W	2a	Stc,Sty	ASY76..77
2N3001	50Hz-Thy	30V, 0,25A(Tc=55°), Igt/Ih<0,02/<3mA	2a	USA,Mot,Tag	(2N2323A)
2N3002	50Hz-Thy	=2N3001: 60V	2a		(2N2324A)
2N3003	50Hz-Thy	=2N3001: 100V	2a		(2N2324A)
2N3004	50Hz-Thy	=2N3001: 200V	2a		(2N2326A)
2N3005	50Hz-Thy	=2N3001: Igt/Ih<0,2/<5mA	2a		2N6605, TAG08Y, (2N2323, TAG615-100)
2N3006	50Hz-Thy	=2N3002: Igt/Ih<0,2/<5mA	2a		2N6606, TAG08YY, (2N2324, TAG615-100)
2N3007	50Hz-Thy	=2N3003: Igt/Ih<0,2/<5mA	2a		2N6607, TAG06A, (2N2324, TAG615-100)
2N3008	50Hz-Thy	=2N3004: Igt/Ih<0,2/<5mA	2a		2N8606, TAG08B, (2N2326, TAG615-200)
2N3009	Si-N	S, 40V, 0,2A, 0,36W, <15/25ns	2a	USA,Mot,Sgs	BSS 10..11, BSX19..20, 2N2368..69(A),++
2N301	Ge-P	NF/S-L, 40V, 3A, 50W	23a	USA, Mot	AD149, AUY19..20, 2N2143..48,++
2N3010	Si-N	S, 15V, 0,05A, 0,3W, <12/12ns	2a	USA,Mot,Sgs	BSS 11..12, BSY 17..18, 2N2368..69(A),++
2N3011	Si-N	SS, 30V, 0,2A, 0,36W, <15/20ns	2a	USA,Mot,Mic	BSS 11..12, BSX19..20, 2N2368..69(A),++
2N3011	Si-N			Sgs,Tix,++	—
2N3012	Si-P	S, 12V, 0,2A, 0,36W, <60/75ns	2a	USA,Mot,Mic	BSX36
2N3012	Si-P			Sgs,Tix,++	—
2N3013(R)	Si-N	SS, 40V, 0,2A, 0,36W, <15/25ns	2a	USA,Mot,Mic	BSS 10..11, BSX19..20, 2N2368..69(A),++
2N3013(R)	Si-N			Sgs,Tix,++	—
2N3014	Si-N	SS, 40V, 0,2A, 0,36W, <16/25ns	2a	=2N1313	BSS 10..11, BSX19..20, 2N2368..69(A),++
2N3015	Si-N	S, 60V, 1A, 0,8W, <40/80ns	2a	USA,Mot,Tix	BSS27, BSV77, BSV95, 2N5189,++
2N3016	Si-N	NF/S, 100V, 2,5A, 3,3W(Tc=25°)	2a	USA	BSX64, 2N4239, 2SC696(A), 2SC2214
2N3017	Si-N	=2N3016: 5A	49m	USA	(BD243C, BD539C, BD953, 2SD613,++)
2N3018	Si-N	=2N3016: 10A, 25W(Tc=25°)	49m	USA	2N5288..69, 2N5542
2N3019(S)	Si-N	Um, 140V, 1A, 0,8W, >100MHz, B>100	2a	USA,EUR,Mic	BSS43, BSW68, 2SC1860
2N301A	Ge-P	=2N301: 60V	23a		AL102..103, AUY19..20, 2N2144..48,++

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2N302	Ge-P	HF/S, 30V, 0,2A, 0,15W, >7MHz	2a	Csr,Etc	ASY26, 2N3323..25
2N3020(S)	Si-N	=2N3019: B>40	2a	USA,EUR,Mic	BSS43, BSW68, 2SC1860
2N3021	Si-P	NF/S-L, 30V, 3A, 25W, >60MHz, B>20	23a	USA,Mot,Tix	2SA1141, 2SA1146, 2SA1186, 2SA1292, ++
2N3022	Si-P	=2N3021: 45V	23a		2SA1141, 2SA1146, 2SA1186, 2SA1292, ++
2N3023	Si-P	=2N3021: 60V	23a		2SA1141, 2SA1146, 2SA1188, 2SA1292, ++
2N3024	Si-P	=2N3021: B>50	23a		2SA1141, 2SA1146, 2SA1186, 2SA1292, ++
2N3025	Si-P	=2N3021: 45V, B>50	23a		2SA1141, 2SA1148, 2SA1186, 2SA1292, ++
2N3026	Si-P	=2N3021: 80V, B>50	23a		2SA1141, 2SA1146, 2SA1186, 2SA1292, ++
2N3027	F-Thy	30V, 0,5A(Tc=100°), Igt<0,2mA	2a	USA,Mot,Tag	(TAG64Y, BRX44, BR103, TAG60Y, TAG62Y)
2N3028	F-Thy	=2N3027: 60V	2a		(TAG64F, BRX46, BRX51, TAG60F, TAG62F)
2N3029	F-Thy	=2N3027: 100V	2a		(TAG64A, BRX48, BRX51, TAG60A, TAG82A)
2N303	Ge-P	=2N302: >14MHz	~1a	Csr,Etc	ASY26, 2N3323..25
2N3030	F-Thy	=2N3027: Igt<0,02mA	2a		—
2N3031	F-Thy	=2N3028: Igt<0,02mA	2a		—
2N3032	F-Thy	=2N3029 Igt<0,02mA	2a		—
2N3033	Si-N	SS, 160V, 0,02A, 0,3W, <5/-ns	2a	Sca,Spe,Tix	—
2N3034	Si-N	=2N3033: 120V	2a	Sca,Spe,Tix	—
2N3035	Si-N	=2N3033: 90V	2a	Sca,Spe,Tix	—
2N3036	Si-N	NF/S, 120V, 1,2A, 0,8W, 89/575ns	2a	USA,Tix	2N2102, 2N2405, 2N3019..20
2N3037	Si-N	NF/S, 120V, 0,5A, 0,36W, >50MHz	24b	Tix	BCX22, 2N3700..01, 2SD2235, 2SD667, ++
2N3036	Si-N	=2N3037: 100V	24b	Tix	BC639, BCX24, 2N3700..01, 2SD667, ++
2N3039	Si-P	NF/S, 50V, 0,5A, 0,36W, >50MHz	24b	Tix	BC327, BC638, BC640, 2SB647, ++
2N3040	Si-P	=2N3039: 40V	24b	Tix	BC327, BC638, BC836, BC640, ++
2N3043	Si-N	=2N2639: 0,35W	10-FLF	Mot,Ray,Tix	—
2N3044	Si-N	=2N2640: 0,35W	10-FLF	Mot,Ray,Tix	—
2N3045	Si-N	=2N2641: 0,35W	10-FLF	Mot,Ray,Tix	—
2N3046	Si-N	=2N2642: 0,35W	10-FLF	Mot,Ray,Tix	—
2N3047	Si-N	=2N2643: 0,35W	10-FLF	Mot,Ray,Tix	—
2N3048	Si-N	=2N2644: 0,35W	HO-FLF	Mot,Ray,Tix	—
2N3049	Si-P	Dual, ra, 25V, 0,1A, 0,35W, >60MHz	10-FLF	Mot,Sem,Sty	—
2N3050	Si-P	Dual, ra, 25V, 0,1A, 0,35W, >60MHz	10-FLF	Mot,Sem,Sty	—
2N3051	Si-P	Dual, ra, 25V, 0,1A, 0,35W, >60MHz	10-FLF	Mot,Sem,Sty	—
2N3052	Si-N	Dual, 35V, 0,2A, 0,35W, >200MHz	10-FLF	Ssi,Tix	—
2N3053(S)	Si-N	NF-Tr, 60V, 0,7A, 1W, >100MHz	2a	USA,EUR,Mic	BC140..141, BC300..302, 2N2218..19, ++
2N3053A	Si-N	=2N3053: 60V	2a	Mot,Rca	BC140..141, BC300..302, 2N2218..19A, ++
2N3054(S)	Si-N	NF-L, 90V, 4A, 25W, >0,8MHz	22a	USA,EUR,Mic	BD243B, BD539C, 2N3767, 2SD712, ++
2N3054(S)	Si-N			Sie	—
2N3054A	Si-N	=2N3054: 75W, >3MHz	22a	Mot	BD243B, BD539C, 2N3787, 2SD712, ++
2N3055(E,H,3,U)	Si-N	NF/S-L, 100V, 15A, 115W, >2,5MHz	23a	USA,EUR	BD317, BD745C, BDW51C, 2N5629..31, ++
2N3055A	Si-N	<4,5/9μs	23a	Mot	—
2N3055C,V	Si-N	=2N3055: 60V	23a	Sgs	BD315, BD745B, BDW51B, 2N5629..F1255231, ++
2N3056	Si-N	Uni, 100V, 1A, 0,4W, >80MHz, B>40	2a	USA,Fch	BC639, BCX24, 2N3700..01, 2SD667, ++
2N3056A	Si-N	=2N3058: 140V	2a		2N3700..01, 2SC2363, 2SC3228
2N3057	Si-N	=2N3056: B>100	2a	USA,Fch	BC639, BCX24, 2N3700..01, 2SD667, ++
2N3057A	Si-N	=2N3056: 140V, B>100	2a		2N3700..01, 2SC2383, 2SC3228
2N3056	Si-P	S, Chopper, 6/6/6V, 0,1A, 0,4W	2a	USA,Tdy	—
2N3059	Si-P	S, Chopper, 10/10/10V, 0,1A, 0,4W	2a	USA,Tdy	—
2N306	Ge-N	NF/S, 30V, 250mA, 0,05W	2a	Csr,Etc	(AC127, ASY28..29)
2N3060	Si-P	S, Chopper, 70/60/30V, 0,1A, 0,4W	2a	USA,Tdy	—
2N3061	Si-P	S, Chopper, 70/60/30V, 0,1A, 0,4W	2a	USA,Tdy	—
2N3062	Si-P	S, Chopper, 90/80/40V, 0,1A, 0,4W	2a	Tdy	—
2N3063	Si-P	S, Chopper, 90/80/40V, 0,1A, 0,4W	2a	Tdy	—
2N3064	Si-P	S, Chopper, 110/100/50V, 0,1A, 0,4W	2a	Tdy	—
2N3065	Si-P	S, Chopper, 110/100/50V, 0,1A, 0,4W	2a	Tdy	—
2N3066(A)	N-FET	Uni, 50V, Idss>0,8mA, Up<9,5V	2b	Sol,Tix	—
2N3067(A)	N-FET	Uni, 50V, Idss>0,2mA, Up<4,5V	2b	Sol,Tix	—
2N3068(A)	N-FET	Uni, 50V, Idss>0,05mA, Up<2,2V	2b	Sol,Tix	—
2N3069(A)	N-FET	Uni, 50V, Idss>2mA, Up<10V	2b	Nsc,Sol,Tix	—
2N307(A,B)	Ge-P	NF/S-L, 35V, 5A, 106W	23a	USA,Mot	AL102..103, AUY21..22, 2N3611..18, ++
2N3070(A)	N-FET	Uni, 50V, Idss>0,5mA, Up<5V	2b	Nsc,Sol,Tix	—
2N3071	N-FET	Uni, 50V, Idss>0,1mA, Up<2,5V	2b	Nsc,Sol,Tix	—
2N3072	Si-P	S, 60V, 0,5A, 0,8W, >130MHz, <40/100ns	2a	USA,Mot,Sgs	BSW23, 2N2904..05(A), 2N3468, 2SA742, ++
2N3073	Si-P	=2N3072: 0,36W	2a	USA,Mot,Sgs	BSW24, 2N2906..07(A), 2N4026..29
2N3074	Ge-P	HF, 30V, 0,02A, 0,14W	5g	Amp,Sty	AF139, AF239(S), 2N3283..68
2N3075	Ge-P	HF, 35V, 0,02A, 0,14W	5g	Amp,Sty	AF139, AF239(S), 2N3283..86
2N3076	Si-N	S-L, 140V, 10A, 125W, >50MHz		Sca,SSi,Trw	—

2N3077	Si-N	Uni, ra, 80V, 0,05A, 0,36W, >60MHz, B>80	2a	USA	2SC1775(A), 2SC2240, 2SC2390, 2SC2459,++
2N3078	Si-N	=2N3077: B>25	2a	USA	2SC1775(A), 2SC2240, 2SC2390, 2SC2459,++
2N3079	Si-N	S-L, 200/200V, 5A, 150W, >2MHz	33a	Del,Spc	—
2N308	Ge-P	HF, 20V, 300mA, 0,03W	2a	Csr,Etc	AF124..127, AF200
2N3080	Si-N	=2N3079: 300/300V	38a	Del,Spc	—
2N3081	Si-P	S, 70V, 0,6A, 0,8W, >150MHz, <60/175ns	2a	USA, Mot	BSW40, 2N4031, 2N4033, 2N4036
2N3082	Si-N	Dual, Chopper, 25V, 0,1A, 0,5W	TO-77	Gen,Tho	—
2N3083	Si-N	Dual, Chopper, 25V, 0,1A, 0,5W	TO-77	Gen,Tho	—
2N3084	N-FET	Uni, 30V, Idss>0,8mA, Up<10V	2f	Sol,Tdy	—
2N3085	N-FET	Uni, 30V, Idss>0,8mA, Up<10V	2f	Sol,Tdy	—
2N3086	N-FET	Uni, 40V, Idss>0,8mA, Up<10V	2f	Sol,Tdy	—
2N3087	N-FET	Uni, 30V, Idss>0,8mA, Up<10V	2f	Sol,Tdy	—
2N3088(A)	N-FET	Uni, 15V, Idss>0,5mA, Up<5V	2f	Sol,Tdy	—
2N3089(A)	N-FET	Uni, 15V, Idss>0,5mA, Up<5V	2f	Sol,Tdy	—
2N309	Ge-P	HF, 20V, 300mA, 0,03W	2a	Csr,Etc	AF124..127, AF200
2N31	Ge-P	NF/HF, 30V, 7mA, 0,1W		Gen	AF124..127, AF200
2N310	Ge-P	HF, 30V, 300mA, 0,03W	2a	Csr,Etc	AF124..127, AF200
2N3107	Si-N	NF/S, 100V, 1A, 0,8W, >70MHz, B>100	2a	USA,Sgs,Tix	BC141, BSW66, BSX46..47, 2N1990,++
2N3108	Si-N	=2N3107: B>40	2a	USA,Sgs,Tix	BC141, BSW66, BSX46..47, 2N1990,++
2N3109	Si-N	=2N3107: 80V	2a	USA,Sgs,Tix	BC140, BSW65, BSX45..47, 2N1990,++
2N311	Ge-P	S, 15V, 0,075W	2a	Csr,Etc,Sty	ASY26..27, ASY76..77
2N3110(S)	Si-N	=2N3107: 80V, B>40	2a	USA,Sgs,Tix	BC140, BSW65, BSX45..47, 2N1990,++
2N3112	P-FET	Uni, 20V, Idss>0,035mA, Up<4V	5n	Six	2N5797
2N3113	P-FET	=2N3112:	2a	Six	2N5797
2N3114(S)	Si-N	Vid, 150V, 0,2A, 0,8W, >40MHz	2a	USA,Mot,Tix	BF257..259, BF857..859, BFR57..59,++
2N3115	Si-N	=2N2958: 0,4W	2a	USAMot,Mic	BSS26, BSV59, BSX49, 2N2221..22(A),++
2N3116	Si-N	=2N2959: 0,4W	2a	USA,Mot,Mic	BSS26, BSV59, BSX49, 2N2221..22(A),++
2N3117	Si-N	NF/S, ra, 80V, 0,05A, 0,36W, >80MHz	2a	USA,Sgs,Tix	2SC1775(A), 2SC2240, 2SC2390, 2SC2459,++
2N3118	Si-N	FM/VHF-A/Tr, 85V, 0,5A, PQ>0,4W(150MHz)	2a	USA,Rca	BFW47, 2N3553, 2SC2852
2N3119	Si-N	S, 100V, 0,5A, 1W, >250MHz, <40/700ns	2a	USA,Rca	BSW39, 2N3723
2N312	Ge-N	S, 15V, 0,2A, 0,075W	2a	Csr,Etc,Sty	ASY26..29, ASY73..75
2N3120	Si-P	S, 45V, 0,5A, 0,8W, >130MHz, <40/100ns	2a	USA,Mot,Sgs	2N3468, 2SA717, 2SA742
2N3121	Si-P	=2N3120: 0,36W	2a	USA,Mot,Sgs	BSW24, BSX36
2N3122	Si-N	NF-Tr, 50V, 0,5A, 0,8W, >60MHz	2a	USA	BC140..141, BC300..302, 2N3053,++
2N3123	Si-N	HF/S, 80V, 0,5A, 0,8W, >400MHz	2a	Sty	BFW47, BSV77, BSV95, 2N3553,++
2N3124	Ge-P	NF/S-L, 40V, 15A, 90W	23a	Cen,Csr,Gpd	AUY29, 2N1549..60
2N3125	Ge-P	NF/S-L, 80V, 3,3A, 90W	23a	Cen,Csr,Gpd	AL102..103, AUY20, 2N2141, 2N2146,++
2N3126	Ge-P	NF/S-L, 100V, 15A, 90W	23a	Cen,Csr,Gpd	2N1552, 2N1556, 2N1560
2N3127	Ge-P	VHF/UHF, 25V, 0,05A, 0,1W, >400MHz	5g	USA, Mot	AF139, AF239(S), 2N3283..86
2N3128	Si-N	Min, NF, 20V, 0,1A, 0,15W, >80MHz	≈7c	Nsc	BC122..123, BC146
2N3129	Si-N	Min, NF, 45V, 0,1A, 0,15W, >60MHz	≈7c	Nsc	BC123
2N313	Ge-N	HF, 15V, 0,02A, 0,065W, 5MHz	2a	Gen	—
2N3130	Si-N	Min, NF, 80V, 0,1A, 0,15W, >60MHz	≈7c	Nsc	—
2N3131	Si-N	Min, S, 40V, 0,1A, 0,15W, >250MHz	≈7c	Nsc	—
2N3132	Ge-P	NF/S-L, 100V, 5A, 90W	23a	Cen,Sty	AL102..103, 2N1542..43, 2N1547..48,++
2N3133(S)	Si-P	HF/S, 50V, 0,6A, 0,6W, 26/70ns, B>40	2a	USA,Mot,Phi	2N3468, 2SA717, 2SA742
2N3134(S)	Si-P	=2N3133: B>100	2a	USA,Mot,Phi	2N3468, 2SA717, 2SA742
2N3135	Si-P	=2N3133: 0,4W	2a	USA,Mot,Phi	BSW24, BSX36
2N3136	Si-P	=2N3133: 0,4W, B>100	2a	USA,Mot,Phi	BSW24, BSX36
2N3137	Si-N	VHF/UHF-A/Tr, 40V, 0,15A, PQ=0,6W(250MHz)	2a	USA,Mot,Tho	BFW16..17, BFS50, BFR36, 2SC2852,++
2N3137T	Si-N	=2N3137: 0,5A	2a	Trx	BFS50, MRF629, 2N3946, 2SC2852,++
2N3138	Si-N	S-L, 65V, 2A, 20W	49m	Sca,Sem,Ssi	2N5002, 2N5004, 2N5284..85
2N3139	Si-N	S-L, 140V, 2A, 20W	49m	Sca,Sem,Ssi	—
2N314	Ge-N	=2N313: 8MHz	2a	Gen	—
2N3140	Si-N	S-L, 65V, 2A, 20W	49m	Sca,Sem,Ssi	2N5002, 2N5004, 2N5284..85
2N3141	Si-N	S-L, 140V, 2A, 20W	49m	Sca,Sem,Ssi	—
2N3142	Si-N	S-L, 65V, 2A, 20W	49a	Sca,Sem,Ssi	2N5002, 2N5004, 2N5284..85
2N3143	Si-N	S-L, 140V, 2A, 20W	49a		—
2N3144	Si-N	S-L, 85V, 2A, 20W	49a		2N5002, 2N5004, 2N5284..85
2N3145	Si-N	S-L, 140V, 2A, 20W	49a		—
2N3146	Ge-P	S-L, 150V, 15A, 150W	23a	Csr,Gpd,Sty	—
2N3147	Ge-P	=2N3146: 180V	23a	Csr,Gpd,Sty	—
2N3148	Ge-P	S, 11V, 0,05A, 0,025W, >25MHz	37d	Spr	ASZ21, 2N705, 2N960..967, 2N2955..57
2N3149	Si-N	S-L, 80/80V, 70A, 300W	49m	USA	2N9309..11
2N315	Ge-P	S, 20V, 0,2A, 0,1W	2a	USA	2N1305
2N3150	Si-N	=2N3149: 100/100V	49m	USA	2N9309..11

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2N3151	Si-N	=2N3149: 150/150V	49m	USA	—
2N3152	Si-N	S, 120V, 0,1A, 2,5W(Tc=100°), >200MHz	49a	Sca,Spe,Sty	—
2N3153	Si-N	Chopper, 15/15/15V, 0,1A, 0,3W, >30MHz	2a	Idl,Tdy	—
2N3154	Ge-P	S-L, 40V, 3A, 38W, B>60		Gpd,Stc	—
2N3155	Ge-P	=2N3154: 60V			—
2N3156	Ge-P	=2N3154: 60V			—
2N3157	Ge-P	=2N3154: 100V			—
2N3158	Ge-P	=2N3154: B>30			—
2N3159	Ge-P	=2N3154: 60V, B>30			—
2N315A,B	Ge-P	=2N315: 30V, 0,15W	2a		2N1305
2N318	Ge-P	S, 20V, 0,2A, 0,1W	2a	USA	2N1307
2N3160	Ge-P	=2N3154: 60V, B>30			—
2N3161	Ge-P	=2N3154: 100V, B>30			—
2N3162	Si-N	gep, 45V, 0,3W, B>50	5	Fch,Sty	—
2N3163	Si-P	S-L, 40V, 3A, 85W	49m	Sca,SSi	2N5003, 2N5005, 2N5286..87
2N3164	Si-P	=2N3163: 60V	49m		2N5003, 2N5005, 2N5286..87
2N3165	Si-P	=2N3163: 80V	49m		2N5003, 2N5005, 2N5286..87
2N3166	Si-P	=2N3163: 100V	49m		2N5003, 2N5005, 2N5286..87
2N3167	Si-P	=2N3163:			(BD246, BDV92, 2SB688, 2SB775..776,++)
2N3168	Si-P	=2N3163: 60V			(BD246A, BDV94, 2SB688, 2SB775..776++)
2N3169	Si-P	=2N3163: 80V			(BD246B, BDV94, 2SB688, 28B775..776++)
2N316A	Ge-P	=2N316: 30V, 0,15A	9a		2N1307
2N317	Ge-P	S, 20V, 0,2A, 0,1W	2a	USA	2N1309
2N3170	Si-P	=2N3163: 100V			(BD246C, BDV96, 2SB688, 2SB775..776++)
2N3171	Si-P	=2N3163: 75W	23a	USA	BD246, BDV92, BDX92, 2SA980, ++
2N3172	Si-P	=2N3163: 60V, 75W	23a		BD246A, BDV92, BDX92, 2SA980, ++
2N3173	Si-P	=2N3163: 60V, 75W	23a		BD246B, BDV94, BDX94, 2SA980, ++
2N3174	Si-P	=2N3163: 100V, 75W	23a		BD246C, BDV86, BDX96, 2SA960, ++
2N3175	Si-P	S-L, 40V, 5A, 85W	49m	Sca,Ssi	2N5003, 2N5005, 2N5286..87
2N3176	Si-P	=2N3175: 60V	49m		2N5003, 2N5005, 2N5286..87
2N3177	Si-P	=2N3175: 60V	49m		2N5003, 2N5005, 2N5286..87
2N3178	Si-P	=2N3175: 100V	49m		2N5003, 2N5005, 2N5286..87
2N3179	Si-P	=2N3175:			(BD248, BDV92, 2SB688, 2SB775..776,++)
2N317A	Ge-P	=2N317: 25V, 0,15W	2a		2N1309
2N318	Opto				—
2N3160	Si-P	=2N3175: 60V			(BD246A, BDV92, 2SB688, 2SB775..776++)
2N3181	Si-P	=2N3175: 60V			(BD246B, BDV94, 2SB688, 2SB775..776++)
2N3182	Si-P	=2N3175: 100V			(BD246C, BDV96, 2SB688, 2SB775..776++)
2N3183	Si-P	=2N3175: 75W	23a	USA	BD246, BDV92, BDX92, 2SA960, ++
2N3184	Si-P	=2N3175: 60V, 75W	23a		BD246A, BDV92, BDX92, 2SA980, ++
2N3185	Si-P	=2N3175: 60V, 75W	23a		BD246B, BDV94, BDX94, 2SA980, ++
2N3188	Si-P	=2N3175: 100V, 75W	23a		BD246C, BDV96, BDX96, 2SA980, ++
2N3187	Si-P	S-L, 40V, 5A, 85W	49m	Sca,Ssi	2N5003, 2N5005, 2B5288..87
2N3188	Si-P	=2N3187: 60V	49m		2N5003, 2N5005, 2B5288..87
2N3189	Si-P	=2N3187: 60V	49m		2N5003, 2N5005, 2B5288..87
2N319	Ge-P	NF-Tr, 25V, 0,5A, 0,225W, B>25	2a(B=case)	USA,Gen,Mot	AC128, AC153, AC188
2N3190	Si-P	=2N3187: 100V			2N5003, 2N5005, 2B5288..87
2N3191	Si-P	=2N3187:			(BD248, BDV92, 28B688, 2SB775..776,++)
2N3192	Si-P	=2N3187: 60V			(BD246A, BDV92, 2SB688, 2SB775..776++)
2N3193	Si-P	=2N3187: 60V			(BD246B, BDV94, 2SB688, 2SB775..776++)
2N3194	Si-P	=2N3187: 100V			(BD246C, BDV96, 2SB686, 2SB775..776++)
2N3195	Si-P	=2N3187: 75W	23a	USA	BD246, BDV92, BDX92, 2SA960, ++
2N3196	Si-P	=2N3187: 60V, 75W	23a		BD246A, BDV92, BDX92, 2SA980, ++
2N3197	Si-P	=2N3187: 60V, 75W	23a		BD246B, BDV94, BDX94, 2SA960, ++
2N3196	Si-P	=2N3187: 100V, 75W	23a		BD246C, BDV96, BDX96, 2SA960, ++
2N3199	Si-P	S-L, 40V, 3A, 40W	49m	Ssi,Tra	2N5003, 2N5005, 2N5288..87
2N32(A)	Ge-P	S, 30V, 300mA, 0,05W	2a	Rca	(AC125..F12570128, AC151, ASY48)
2N320	Ge-P	=2N319: B>34	2a(B=case)	USA,Gen,Mot	AC128, AC153, AC188
2N3200	Si-P	=2N3199: 60V	49m		2N5003, 2N5005, 2N5286..87
2N3201	Si-P	=2N3199: 60V	49m		2N5003, 2N5005, 2N5286..87
2N3202	Si-P	=2N3199: 8,7W(Tc=25°)	2a	Ssi,Tra,++	BSS46, BUY90, 2N6190..93
2N3203	Si-P	=2N3199: 60V, 8,7W(Tc=25°)	2a		BSS46, BUY90, 2N6190..93
2N3204	Si-P	=2N3199: 60V, 8,7W(Tc=25°)	2a		BSS46, BUY90, 2N6190..93
2N3205	Si-P	S-L, 40V, 2A, 40W	49m	Sca,Ssi,Tra	2N5003, 2N5005, 2N5286..87
2N3206	Si-P	=2N3205: 60V	49m		2N5003, 2N5005, 2N5286..87
2N3207	Si-P	=2N3205: 100V	49m		2N5003, 2N5005, 2N5288..87

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2N3208	Si-P	NF/S, 40V, 2A, 8,7W(Tc=25°)	2a	USA	BSS46, BUY90, 2N6190..93
2N3209	Si-P	S, 20V, 0,2A, 0,36W, <60/90ns	2a	USA, Sgs, Tix	BSW24, BSX36, 2N4125..26
2N321	Ge-P	=2N319: B>53	2a(B=case)	USA, Gen, Mot	AC128, AC153, AC188
2N3210	Si-N	S, 40V, 0,5A, 0,36W, <40/40ns	2a	USA, Mot	BSS10, BSX..26, BSX39, 2N3261
2N3211	Si-N	S, 40V, 0,5A, 0,36W, <40/40ns	2a	USA, Mot	BSS10, BSX..26, BSX39, 2N3261
2N3212	Ge-P	NF/S-L, 100V, 5A, 14W	43m	Del, Gpd, Stc	—
2N3213	Ge-P	=2N3212: 80V	43m		—
2N3214	Ge-P	=2N3212: 60V	43m		—
2N3215	Ge-P	=2N3212: 40V	43m		—
2N3216	Ge-P	NF/S, 20/10/20V, 0,5A, 0,15W, >9MHz	2a	Cen, Stc	(ASY76..77, 2N118..90)
2N3217	Si-P	Chopper, 15/10/15V, 0,1A, 0,4W	2a	USA	2N2944
2N3216	Si-P	Chopper, 25/20/25V, 0,1A, 0,4W	2a	USA	2N2945
2N3219	Si-P	Chopper, 40/35/40V, 0,1A, 0,4W	2a	USA	2N2946
2N322	Ge-P	NF-Tr, 18V, 0,5A, 0,225W, B>34	2a(B=case)	USA, Gen, Mot	AC128, AC153, AC188
2N3220	Si-N	S-L, 100V, 2A, >10MHz, B>20	49a	USA	2N5002, 2N5004, 2N5284..85
2N3221	Si-N	=2N3220: B>40	49a		2N5002, 2N5004, 2N5284..85
2N3222	Si-N	=2N3220: 80V	49a		2N5002, 2N5004, 2N5284..85
2N3223	Si-N	=2N3220: 80V, B>40	49a		2N5002, 2N5004, 2N5264..85
2N3224	Si-P	NF-Tr, 100V, 0,7W, >60MHz, β>20	2a	USA	BSW40, 2N3634..37, 2SA606, 2SA712
2N3225	Si-P	=2N3224: >80MHz, β>40	2a	USA	BSW40, 2N3634..37, 2SA606, 2SA712
2N3226	Si-N	NF-L, 35V, 5A, 75W	23a	Sca, Sol, Ssi	BD245, BDV91, BDX91, 2N4914..15, ++
2N3227	Si-N	SS, 40V, 0,5A, 0,36W, <23/28ns	2a	USA, Mot, Tix	BSS10, BSX26, BSX39, 2N3261
2N3226	50Hz-Thy	200V, 3,2A(Tc=75°), Igt/Ih<15/<20mA	22a	Rca, Sgs, Tag	2N3525, 2N4101, BStC0513L, TAG671-200
2N3229	Si-N	VHF-L, 105V, 2,5A, PQ>15W(150MHz)	49a	Fer, Rca, Ssi	—
2N323	Ge-P	=2N322: B>53	2a(B=case)	USA, Gen, Mot	AC126, AC153, AC188
2N3230	Si-N-Darl	S-L, 80V, 7A, 25W, B>1000		Fer, Rca, Tsc	—
2N3231	Si-N-Darl	=2N3230: 100V		Fer, Rca, Tsc	—
2N3232	Si-N	NF/S-L, 60V, 7,5A, 117W	23a	USA, Mot	BD245A, BD311, BDV91, BDX91, ++
2N3233	Si-N	=2N3232: 100V	23a	USA, Mot	BD245C, BDV95, BDX95, 2N5632..34, ++
2N3234	Si-N	=2N3232: 180V	23a	USA, Mot	BD245D, BDX11, 2N3442, 2SC2260..62, ++
2N3235	Si-N	NF/S-L, 55V, 15A, 117W	23a	USA	BD315, BD545A, BD745A, 2N3055, ++
2N3236	Si-N	NF/S-L, 90V, 15A, 150W	23a	USA	BD317, BD745C, 2N3772, 2N5629..31, ++
2N3237	Si-N	NF/S-L, 90V, 20A, 200W	23a	USA	BDY29, MJ802, 2N3772, 2SD797
2N3236	Si-N	NF/S-L, 80V, 15A, 150W	23a	USA, Mot	BD315, BD545B, BD745B, 2N3772, ++
2N3239	Si-N	NF/S-L, 80V, 15A, 150W	23a	USA, Mot	BD315, BD545B, BD745B, 2N3772, ++
2N324	Ge-P	=2N322: B>72	2a(B=case)	USA, Gen, Mot	AC128, AC153, AC188
2N3240	Si-N	NF/S-L, 180V, 15A, 150W	23a	USA, Mot	BD745F, BDW12, 2N3773, 2SD752, ++
2N3241	Si-N	Uni, 30V, 0,1A, 0,5W, >50MHz, β>70	2a	USA	BC168, BC183, BC236, BC548, ++
2N3241A	Si-N	=2N3241: 0,2A, β>100	2a		BC168, BC183, BC236, BC548, ++
2N3242	Si-N	Uni, 30V, 0,2A, 0,5W, >50MHz, β>100	2a	USA	BC168, BC183, BC236, BC548, ++
2N3242A	Si-N	=2N3242: 40V, 0,3A, β>125	2a		BC167, BC182, BC237, BC547, ++
2N3244(S)	Si-P	S, 40V, 1A, 1W, <50/185ns	2a	USA, Mot, Tix	2N3467..68, 2SA717, 2SA799
2N3245(S)	Si-P	S, 50V, 1A, 1W, <55/165ns	2a	USA, Mot, Tix	2N3468, 2SA717, 2SA799
2N3246	Si-N	Uni, 60V, 0,05A, 0,35W, >60MHz	2a	USA, Nsc	BC174, BC182, BC190, BC546, ++
2N3247	Si-N	=2N3246: Min, 0,15W	≈7c	Upl	—
2N3248	Si-P	S, 15V, 0,2A, 0,36W, >250MHz, <20/80ns	2a	USA, Mot, Nsc	BSX36
2N3249	Si-P	=2N3248: >300MHz	2a	USA, Mot, Nsc	BSX36
2N325	Ge-P	S-L, 35V, 2A, 12W	23a	Syl	AD149, AUY19..20, 2N2137..48, ++
2N3250	Si-P	S, 50V, 0,2A, 0,36W, <70/225ns	2a	Fch, Mot, Nsc	BSW24, 2N2906..07(A)
2N3250	Si-P			Phi, Tix, ++	—
2N3250A	Si-P	=2N3250: 60V	2a		BSW24, 2N2906..07(A)
2N3251	Si-P	S, 50V, 0,2A, 0,36W, <70/250ns	2a	Fch, Mot, Nsc	BSW24, 2N2906..07(A)
2N3251	Si-P			Phi, Tix, ++	—
2N3251A	Si-P	=2N3251: 80V	2a		BSW24, 2N2906..07(A)
2N3252(S)	Si-N	S, 80V, 1A, 1W, <45/70ns	2a	Fch, Mot, Nsc	BSS27, BSV77, BSV95, 2N5189, ++
2N3252(S)	Si-P			Phi, Tix, ++	—
2N3253(S)	Si-N	S, 75V, 1A, 1W, <50/70ns	2a	=2N3253	BSV95, 2N3735, 2SC1069
2N3254	F-Thy	15V, 0,25A(Ta=55°C), Igt/Ih<0,02/<2mA	2a	Mot, Ssi, Uni	(2N2322A)
2N3255	F-Thy	=2N3254: 30V	2a		(2N2323A)
2N3256	F-Thy	=2N3254: 80V	2a		(2N2324A)
2N3257	F-Thy	=2N3254: Igt/Ih<0,2/<3mA	2a		BRY58/30, TAG08Y, 2N6605, (2N2322, TIC44)
2N3258	F-Thy	=2N3255: Igt/Ih<0,2/<3mA	2a		BRY58/30, TAG08Y, 2N6605, (2N2323, TIC44)
2N3259	F-Thy	=2N3256: Igt/Ih<0,2/<3mA	2a		BRY58/60, TAG08YY, 2N66065, (TIC46)
2N328	Ge-N	NF/S-L, 35V, 2A, 7W	23a	USA	2N1218
2N3280	Si-N	S-L, 200/200V, 30A, +C12634 200W	49m	Idi, Stc	2N6324..25
2N3261	Si-N	SS, 40V, 0,5A, 0,3W, <13/16ns	2a	USA, Fer	BSS10, BSX26, BSX39

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2N3262	Si-N	S, 100V, 1,5A, 1W, <40/750ns	2a	USA,Fer,Tix	2SD854
2N3263	Si-N	S-L, 150V, 25A, 84W, >20MHz		USA,Rca	—
2N3264	Si-N	=2N3263: 120V		USA,Rca	—
2N3265	Si-N	=2N3263: 125W	49m	USA,Rca,Tix	2N2817..18, 2N2821..22
2N3266	Si-N	=2N3263: 120V, 125W	49m	USA,Rca,Tix	2N2817..18, 2N2821..22, 2N5539
2N3267	Ge-P	UHF, 15V, 0,02A, 0,075W, >900MHz	5g	Ssi	AF139, AF239(S), 2N3283..66
2N3268	Si-N	Uni, 45V, 0,025A, 0,15W, >2,5MHz	2a	USA	BC187, BC182, BC237, BC547, ++
2N327(A,B)	Si-P	Uni, 40..50V, 0,05..0,1A, 0,33..0,4W	2a	USA	(BC212, BC257, BC307, BC557, ++)
2N3273	50Hz-Thy	100V, 2,2A(Tc=85°), Igt/Ih<0,2/<2mA	2a	Ssi,Uni	(TAG106A, C106A1, X0403A TAG106A)
2N3274	50Hz-Thy	=2N3273: 200V	2a		(TAG106B, C106B1, X0403B, TAG108B)
2N3275	50Hz-Thy	=2N3273: 300V	2a		(TAG106C, C106C1, X0403C, TAG106C)
2N3276	50Hz-Thy	=2N3273: 400V	2a		(TAG106D, C106D1, X0403D, TAG106D)
2N3277	P-FET	Uni, 25V, Idss>0,15mA, Up<5V	5n	Fch,Isi,Sol	2N5473..74, 2N5797
2N3278	P-FET	Uni, 25V, Idss>0,4mA, Up<8V	5n	Fch,Isi,Sol	BF320A, 2N3809, 2N3820, 2N5475
2N3279	Ge-P	VHF-V/M/O, ra, 30V, 0,05A500MHz	5g	Mot,Ssi,Sty	AF139, AF239(S)
2N328(A,B)	Si-P	Uni, 30..50V, 0,05..0,1A, 0,33..0,4W	2a	USA	(BC212, BC257, BC307, BC557, ++)
2N3280	Ge-P	VHF-V/M/O, ra, 30V, 0,05A, 500MHz	5g	Mot,Ssi,Sty	AF139, AF239(S)
2N3281	Ge-P	VHF-V/M/O, ra, 30V, 0,05A, 400MHz	5g	Mot,Ssi,Sty	AF139, AF239(S)
2N3282	Ge-P	VHF-V/M/O, ra, 30V, 0,05A, 400MHz	5g	Mot,Ssi,Sty	AF139, AF239(S)
2N3283	Ge-P	VHF-V/M/O, ra, 25V, 0,05A, 400MHz	5g	Mot,Ssi,Sty	AF139, AF239(S)
2N3284	Ge-P	VHF-V/M/O, ra, 25V, 0,05A, 400MHz	5g	Mot,Ssi,Sty	AF139, AF239(S)
2N3285	Ge-P	VHF-V/M/O, ra, 20V, 0,05A, 400MHz	5g	Mot,Ssi,Sty	AF139, AF239(S)
2N3286	Ge-P	VHF-V/M/O, ra, 20V, 0,05A, 400MHz	5g	Mot,Ssi,Sty	AF139, AF239(S)
2N3287	Si-N	VHF-V/M/O, 40V, 0,05A, 600MHz	5g	Mot,Sca,Ssi	BF310, BF314, BF502, BF505, BF507++
2N3266	Si-N	VHF-V/M/O, 40V, 0,05A, 600MHz	5g	Mot,Sca,Ssi	BF310, BF314, BF502, BF505, BF507++
2N3239	Si-N	VHF-V/M/O, 30V, 0,05A, 500MHz	5g	Mot,Sca,Ssi	BF310, BF314, BF502, BF505, BF507++
2N329(A,B)	Si-P	Uni, 20..50V, 0,05..0,1A, 0,33..0,4W	2a	USA	(BC212, BC257, BC307, BC557, ++)
2N3290	Si-N	VHF-V/M/O, 30V, 0,05A, 500MHz	5g	Mot,Sca,Ssi	BF310, BF314, BF502, BF505, BF507++
2N3291	Si-N	VHF-V/M/O, 25V, 0,05A, 600MHz	5g	Mot,Sca,Ssi	BF310, BF314, BF502, BF505, BF507++
2N3292	Si-N	VHF-V/M/O, 25V, 0,05A, 600MHz	5g	Mot,Sca,Ssi	BF310, BF314, BF502, BF505, BF507++
2N3293	Si-N	VHF-V/M/O, 20V, 0,05A, 800MHz	5g	Mot,Sca,Ssi	BF310, BF314, BF502, BF505, BF507++
2N3294	Si-N	VHF-V/M/O, 20V, 0,05A, 600MHz	5g	Mot,Sca,Ssi	BF310, BF314, BF502, BF505, BF507++
2N3295(S)	Si-N	HF-Tr, 80V, 0,25A, PEP=0,3W(30MHz)	2a	Mot,Sca,Ssi	MRF402, MRF8003
2N3296	Si-N	HF-Tr/E, 80V, 0,7A, PEP=3W(30MHz)	49m	Mot,Sca,Ssi	—
2N3297	Si-N	HF-L, 80V, 1,5A, PEP=12W(30MHz)	23a	Mot,Sca,Ssi	—
2N3298	Si-N	HF-O/Tr, 25V, 0,1A, PO>0,06W(80MHz)	2a	Mot,Sca,Ssi	BFX59
2N3299(S)	Si-N	S, 80V, 0,5A 0,8W, <60/150ns, B>40	2a	USA,EUR	BSS27, BSV77, BSV95, 2N5189, ++
2N33	Ge-P	HF, 15V, 50mA, 0,03W	2a	Rca	AF124..127, AF200
2N330(A)	Si-P	Uni, 20..50V, 0,05A, 0,33..0,39W	2a	USA	(BC212, BC257, BC307, BC557, ++)
2N3300(S)	Si-N	=2N3299: B>100	2a	USA,EUR	BSS27, BSV77, BSV95, 2N5189, ++
2N3301	Si-N	=2N3299: 0,36W	2a	USA,EUR	BSS26, BSV59, BSX49, 2N4014, ++
2N3302	Si-N	=2N3299: 0,36W, B>100	2a	USA,EUR	BSS26, BSV59, BSX49, 2N4014, ++
2N3303	Si-N	S/Tr, 25V, 1A, 0,6W, >450MHz, <15/25ns	2a	USA,EUR	BSS28..29, BSV69, 2N3724A, 2N5189, ++
2N3304	Si-P	S, 6V, 0,1A, 0,3W, >500MHz, <60/60ns	2a	USA,Mot,Tix	BSX36
2N3305	Si-P	Uni, 50V, 0,6W, >20MHz, B>40	2a	USA	BC161, BC303..304, BSW23, 2N2303, ++
2N3306	Si-P	=2N3305: B>100	2a	USA	BC161, BC303..304, BSW23, 2N2303, ++
2N3307	Si-P	VHF-V/M/O, 40V, 0,05A, 0,2W, >300MHz	5g	USA,Mot	BF324, BF414, BF508, BF914, BF936++
2N3308	Si-P	VHF-V/M/O, 30V, 0,05A, 0,2W, >300MHz	5g	USA,Mot	BF324, BF414, BF506, BF914, BF938++
2N3309	Si-N	VHF-Tr/E, 50V, 0,5A, PO>2W(250MHz)	2a	Mot,Tho,Tix	BFS23, BLY34, 2SC2419
2N3309A	Si-N	=2N3309: 80V, PO>2,2W(250MHz)	2a	Mot	BFS23, BLY34, 2SC2419
2N331	Ge-P	NF-Tr, 30V, 0,2W	2a	USA	AC125..126, AC151, 2SB54, 2SB56
2N3310	Si-N	VHF-Tr/E, 35V, 0,2A, 0,3W, >300MHz	≈2a	Mot,Sty	BFR36, BFR98, BFX55, MRF607, ++
2N3311	Ge-P	S-L, 30V, 5A, 170W, B>80	38a	USA, Mot	2N1960..82, 2N2075..82, 2N2491..93
2N3312	Ge-P	=2N3311: 45V	38a	USA, Mot	2N1980..82, 2N2075..82, 2N2491..93
2N3313	Ge-P	=2N3311: 80V	38a	USA, Mot	2N1961..82, 2N2079..80, 2N2491..93
2N3314	Ge-P	=2N3311: B>100	38a	USA, Mot	2N1980..82, 2N2075..82, 2N2491..93
2N3315	Ge-P	=2N3311: 45V, B>100	38a	USA, Mot	2N1980..82, 2N2075..82, 2N2491..93
2N3316	Ge-P	=2N3311: 80V, B>100	38a	USA, Mot	2N1981..82, 2N2079..80, 2N2491..93
2N3317	Si-P	Chopper, 30/30/30V, 0,05A, 0,15W	2a	Sem,Tdy,Upi	2N2946
2N3318	Si-P	Chopper, 15/15/15V, 0,05A, 0,15W	2a	Sem,Tdy,Upi	2N2945
2N3319	Si-P	Chopper, 10/6/10V, 0,05A, 0,15W	2a	Sem,Tdy,Upi	2N2944
2N332(A)	Si-N	Uni, 45V, 0,025A, 0,1 0,5W	2a	USA	BC167, BC182, BC237, BC547, ++
2N3320	Ge-P	S, 15V, 0,1A, 0,06W, <20/35ns	2a	Idi,Ssi,Upi	2N705, 2N960..67, 2N2955..57
2N3321	Ge-P	S, 12V, 0,1A, 0,06W, <20/40ns	2a	Idi,Ssi,Upi	2N705, 2N960..67, 2N2955..57
2N3322	Ge-P	S, 12V, 0,1A, 0,06W, <20/45ns	2a	Idi,Ssi,Upi	2N705, 2N960..67, 2N2955..57
2N3323	Ge-P	AM/FM, 35V, 0,1A, 0,15W, >200MHz	2a	USA, Mot	AF109R, AF139, AF239(S), 2N3283..66

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2N3324	Ge-P	AM/FM, 35V, 0,1A, 0,15W, >200MHz	2a	USA, Mot	AF 109R, AF 139, AF 239(S), 2N3283..86
2N3325	Ge-P	AM/FM, 35V, 0,1A, 0,15W, >200MHz	2a	USA, Mot	AF 109R, AF 139, AF 239(S), 2N3283..86
2N3326	Si-N	S, 60V, 0,8A, 0,8W, >250MHz	2a	USA, Fch, Itt	BSW51..54, BSX32, 2N2218..19(A), ++
2N3327	Si-N	HF-L, 65V, 2A, 20W, >100MHz	49a	Sca, Ssi	BLY59, 2N3375
2N3328	P-FET	Uni, 20V, Idss<1mA, Up<6V	5n	Is+E2953i, Six, Tix	—
2N3329	P-FET	=2N2497	5n	USA, Mot, Tix	→2N2497
2N333(A)	Si-N	Uni, 45V, 0,025A, 0,1..0,5W	2a	USA	BC 187, BC 182, BC 237, BC 547, ++
2N3330	P-FET	=2N2498	5n	USA, Mot, Tix	→2N2498
2N3331	P-FET	=2N2499	5n	USA, Mot, Tix	→2N2499
2N3332	P-FET	=2N2500	5n	USA, Mot, Tix	→2N2500
2N3333	P-FET	Dual, 20V, Idss<1mA, Up<1,6V	10-FLP	Tix	—
2N3334	P-FET	Dual, 20V, Idss<1mA, Up<1,6V	10-FLP	Tix	—
2N3335	P-FET	Dual, 20V, Idss<1mA, Up<1,6V	10-FLP	Tix	—
2N3336	P-FET	Dual, 20V, Idss<1mA, Up<1,6V	10-FLP	Tix	—
2N3337	Si-N	HF/ZF, 40V, 0,05A, 0,3W, >400MHz	5g	Fch, Sgs, ++	BF 198..199, BF 224..225, BF 596..597, ++
2N3336	Si-N	HF/ZF, 40V, 0,05A, 0,3W, >400MHz	5g	Fch, Sgs, ++	BF 198..199, BF 224..225, BF 596..597, ++
2N3339	Si-N	HF/ZF, 40V, 0,05A, 0,3W, >400MHz	5g	Fch, Sgs, ++	BF 198..199, BF 224..225, BF 598..597, ++
2N334(A,B)	Si-N	Uni, 45..60V, 0,025A, 0,1..0,5W	2a	USA	BC 167, BC 182, BC 237, BC 547, ++
2N3340	Si-N	Uni, 30V, 0,03A 0,4W, >70MHz	2a	USA	BC 168, BC 183, BC 238, BC 548, ++
2N3341	Si-P	Uni, 30V, 0,03A, 0,4W, >50MHz	2a	USA	BC 213, BC 258, BC 308, BC 558, ++
2N3342	Si-P	Chopper, 20/8/20V, 0,05A, 0,25W	2a	USA	2N2944
2N3343	Si-P	Chopper, 25/8/25V, 0,05A, 0,25W	2a	USA	2N2944
2N3344	Si-P	Chopper, 30/30/30, 0,05A, 0,25W	2a	USA	2N2948
2N3345	Si-P	Chopper, 50/50/50, 0,05A, 0,25W	2a	USA	2N2946
2N3346	Si-P	Chopper, 50/50/50, 0,05A, 0,25W	2a	USA	2N2946
2N3347	Si-P	Dual, ra, 60V, 0,03A, 0,6W, >60MHz	TO-77	Mic, Nsc, Ray	BFX36, 2N3806..11, 2N4015..16
2N3347	Si-P			Sca, Sgs, Tix	—
2N3348	Si-P	Dual, ra, 60V, 0,03A, 0,6W, >60MHz	TO-77	=2N3347	BFX36, 2N3806..11, 2N4015..16
2N3349	Si-P	Dual, ra, 60V, 0,03A, 0,6W, >60MHz	TO-77	=2N3347	BFX36, 2N3806..11, 2N4015..16
2N335(A,B)	Si-N	Uni, 45..60V, 0,025A, 0,1..0,5W	2a	USA	BC 167, BC 182, BC 237, BC 547, ++
2N3350	Si-P	Dual, ra, 60V, 0,03A, 0,6W, >60MHz	TO-77	=2N3347	BFX36, 2N3806..11, 2N4015..16
2N3351	Si-P	Dual, ra, 60V, 0,03A, 0,6W, >60MHz	TO-99	=2N3347	BFX36, 2N3806..11, 2N4015..16
2N3352	Si-P	Dual, ra, 60V, 0,03A, 0,6W, >60MHz	TO-77	=2N3347	BFX36, 2N3806..11, 2N4015..16
2N336(A)	Si-N	Uni, 45V, 0,025A, 0,1..0,5W	2a	USA	BC 167, BC 182, BC 237, BC 547, ++
2N3365	N-FET	Uni, ra, 40V, Idss>0,8mA, Up<12V	2b	USA, Mot, Tix	—
2N3366	N-FET	Uni, ra, 40V, Idss>0,2mA, Up<7V	2b	USA, Mot, Tix	2N4119
2N3367	N-FET	Uni, ra, 40V, Idss>0,05mA, Up<2,5V	2b	USA, Mot, Tix	2N4118
2N3366	N-FET	Uni, ra, 40V, Idss>2mA, Up<12V	2b	USA, Mot, Tix	2SK113
2N3369	N-FET	Uni, ra, 40V, Idss>0,5mA, Up<12V	2b	USA, Mot, Tix	—
2N337(A)	Si-N	Uni, 45V, 0,02A, 0,1..0,5W	2a	USA	BC 167, BC 182, BC 237, BC 547, ++
2N3370	N-FET	Uni, ra, 40V, Idss>0,1mA, Up<3,2V	2b	USA, Mot, Tix	2N4118
2N3371	Ge-P	VHF, ra, 25V, 0,1A, 0,15W, >400MHz	2a	Idi, Spe, Tix	AF 139, AF 239(S), 2N3283..86
2N3374	Si-N	HF/S, 60V, 0,5A, PQ=2,8W(130MHz)	2a	Sty	BFS 23, BLY34, 2SC2419
2N3375	Si-N	VHF/UHF-L, 65V, 1,5A, PQ>3W(400MHz)	49a	USA, EUR	—
2N3376	P-FET	Uni, 30V, Idss>0,6mA, Up<5V	5n	NSC, Six, ++	—
2N3377	P-FET	=2N3376	≈24	NSC, Six, ++	—
2N3378	P-FET	Uni, 30V, Idss>3mA, Up<5V	5n	NSC, Six, ++	—
2N3379	P-FET	=2N3378	≈24	NSC, Six, ++	—
2N336(A)	Si-N	Uni, 45V, 0,02A, 0,1..0,5W	2a	USA	BC 187, BC 182, BC 237, BC 547, ++
2N3380	P-FET	Uni, 30V, Idss>3mA, Up<9,5V	5n	NSC, Six, ++	—
2N3381	P-FET	=2N3380	≈24	NSC, Six, ++	—
2N3362	P-FET	Uni, 30V, Idss>3mA, Up<5V	5n	NSC, Six, ++	—
2N3363	P-FET	=2N3392	≈24	NSC, Six, ++	—
2N3384	P-FET	Uni, 30V, Idss>15mA, Up<5V	5n	NSC, Six, ++	—
2N3365	P-FET	=2N3384	≈24	NSC, Six, ++	—
2N3366	P-FET	Uni, 30V, Idss>15mA, Up<9,5V	5n	NSC, Six, ++	—
2N3387	P-FET	=2N3366	≈24	NSC, Six, ++	—
2N3388	Si-N	Nix, S, 125V, 2,5mA, 0,6W, >36MHz	2a	SSi, Stc, Tra	BF257..259, BF657..659, 2N5058..59, ++
2N3369	Si-N	Nix, S, 195V, 7mA, 0,6W, >36MHz	2a	SSi, Stc, Tra	BF258..259, BF658..659, 2N5058..59, ++
2N339(A)	Si-N	NF-Tr, 55..60V, 0,06..0,15A	2a	USA	BC 174, BC 190, BC 546, 2SC3245(A), ++
2N3390	Si-N	Uni, 25V, 0,1A, 0,36W, 140MHz, B>400	7c	USA, Mic, Tho	BC 168, BC 183, BC 238, BC 548, ++
2N3391(A)	Si-N	=2N3390: 160MHz, B>250	7c	USA, Mic, Tho	BC 168, BC 183, BC 236, BC 548, ++
2N3392	Si-N	=2N3390: >120MHz, B>150	7c	USA, Mic, Tho	BC 168, BC 183, BC 236, BC 548, ++
2N3393	Si-N	=2N3390: >120MHz, B>90	7c	USA, Mic, Tho	BC 168, BC 183, BC 236, BC 548, ++
2N3394	Si-N	=2N3390: >120MHz, B>55	7c	USA, Mic, Tho	BC 168, BC 183, BC 238, BC 548, ++
2N3395	Si-N	=2N3390: B>150	7c	USA, Mic, Tho	BC 168, BC 183, BC 238, BC 548, ++

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2N3396	Si-N	=2N3390: B>90	7c	USA,Mic,Tho	BC168, BC183, BC238, BC548, ++
2N3397	Si-N	=2N3390: B>55	7c	USA,Mic,Tho	BC168, BC183, BC238, BC548, ++
2N3398	Si-N	=2N3390: B>55	7c	USA,Mic,Tho	BC168, BC163, BC238, BC548, ++
2N3398	Ge-P	UHF, 20V, 7mA, 0,06W, >400MHz	5g	Amp,Ssi,Sty	AF139, AF239(S), 2N3263..68
2N34(A)	Ge-P	NF/S, 25V, 50mA, 0,05W	3a	USA	(AC125..126, AC151, ASY26..27)
2N34/5	Ge-P	NF/S, 40V, 0,1A, 0,15W	2a	Syl	(AC125..126, AC151, ASY48)
2N340(A)	Si-N	NF-Tr, 85V, 0,06A..0,15A	2a	USA	BC546, 2SC2240, 2SC2459, 2SC3245(A), ++
2N3400	Ge-P	S, 20V, 0,1A, 0,15W, <90/260ns	2a	Cen,Sty	2N2635, 2N2955..57
2N3401	Si-P	Chopper, 25/25/25V, 0,1A, 0,25W	2a	Tdy	2N2945
2N3402	Si-N	Uni, 25V, 0,5A, 0,56W, B>75	7c°	USA,Mic,Tho	BC337..338, BC635, BC637, BC639, ++
2N3403	Si-N	=2N3402: B>180	7c°	USA,Mic,Tho	BC337..338, BC635, BC837, BC639, ++
2N3404	Si-N	=2N3402: 50V	7c°	USA,Mic,Tho	BC337, BC637, BC639, 2SD667, ++
2N3405	Si-N	=2N3402: 50V, B>180	7c°	USA,Mic,Tho	BC337, BC637, BC839, 2SD667, ++
2N3406	UJT-P	Iv>8mA	5	Gen	—
2N3407	Si-N	HF, 35V, 0,1A, 0,2W, >300MHz	5g	Mot,Sty	BF198..199, BF224..225, BF598..597, ++
2N3408	Si-P	HF-Tr/E, 40V, 0,5A, 4W, >200MHz	49a	Mot,Sty	—
2N3409	Si-N	Dual, ra, 60V, 0,5A, 0,6W, >250MHz	TO-77	Mot,Sgs,++	—
2N341(A)	Si-N	NF-Tr, 125V, 0,06A..0,15A	2a	USA	BF257, 2SC2240, 2SC2459, 2SC3245(A), ++
2N3410	Si-N	Dual, ra, 80V, 0,5A, 0,6W, >250MHz	TO-77	Mot,Sgs,++	—
2N3411	Si-N	Dual, ra, 60V, 0,5A, 0,6W, >250MHz	TO-77	Mot,Sgs,++	—
2N3412	Ge-P	HF, 20V, 0,1A, 0,06W, >100MHz	2a	Csr,Etc,Idi	2N3283..86, (AF106, AF109R, AF306)
2N3413	Ge-P	S, Chopper, 150/150/150V, 0,2A(ss)	2a	Sca, Sty	—
2N3414	Si-N	=2N3402: 0,38W	7c	USA,Mic,Tho	→2N3402
2N3415	Si-N	=2N3403: 0,38W	7c	USA,Mic,Tho	→2N3403
2N3416	Si-N	=2N3404: 0,38W	7c	USA,Mic,Tho	→2N3404
2N3417	Si-N	=2N3405: 0,36W	7c	USA,Mic,Tho	→2N3405
2N3418	Si-N	NF/S, 85V, 5A, 15W(Tc=100°), B>20	2a	USA,Sgs,Tix	BUX34, BUY80, 2N5338..39
2N3419	Si-N	=2N3418: 125V	2a	USA,Sgs,Tix	BUX34, BUY80, 2N4995..97
2N342(A,B)	Si-N	NF-Tr, 60..85V, 0,06A..0,15A	2a	USA	BC546, 2SC2240, 2SC2459, 2SC3245(A), ++
2N3420	Si-N	=2N3418: B>40	2e	USA,Sgs,Tix	BUX34, BUY80, 2N5336..39
2N3421	Si-N	=2N3418: 125V, B>40	2a	USA,Sgs,Tix	BUX34, BUY80, 2N4895..97
2N3423	Si-N	Dual, 30V, 0,05A, 0,45W, >600MHz	TO-77	USA,Mot,Sgs	BFY84
2N3424	Si-N	Dual, 30V, 0,05A, 0,45W, >600MHz	TO-77	USA,Mot,Sgs	BFY84
2N3425	Si-N	Dual, 40V, 0,4W, >300MHz	TO-77	Fch,Mot,Ray	—
2N3426	Si-N	S, 25V, 1A, 0,6W, >450MHz, <15/25ns	2a	USA,Phi,Sgs	BSS26..29, BSV69, BSX12, 2N3724A++
2N3427	Ge-P	NF/S, 45V, 0,5A, 0,2W, B>100	2a	Mot,Sem,Stc	ASY76..77, 2N1189..90
2N3426	Ge-P	=2N3427: B>150	2a	Mot,Sem,Stc	ASY76..77, 2N1169..90
2N3429	Si-N	S-L, 50V, 5A, 150W	49b	Sem,Whs	2N5387..69
2N343(A,B)	Si-N	NF-Tr, 80..65V, 0,06A..0,15A	2a	USA	BC174, BC180, BC548, 2SC3245(A), ++
2N3430	Si-N	=2N3429: 100V	49b	Sem,Whs	2N5387..89
2N3431	Si-N	=2N3429: 150V	49b	Fsem,Whs	2N5387..69
2N3432	Si-N	=2N3429: 200V	49b	Sem,Whs	2N5387..69
2N3433	Si-N	=2N3429: 250V	49b	Sem,Whs	2N5388..69
2N3434	Si-N	=2N3429: 300V	49b	Sem,Whs	2N5389
2N3435	Si-N	Uni, 80V, 0,25A, 1W, >140MHz	2a	Cen,Sty	BC140..141, BC300..301, 2N2216..19A, ++
2N3436	N-FET	Uni, ra, 50V, Idss>3mA, Up<10	2b	USA, Mot	2N3368, 2SK113
2N3437	N-FET	Uni, ra, 50V, Idss>0,8mA, Up<5	2b	USA, Mot	2N5359
2N3438	N-FET	Uni, ra, 50V, Idss>0,2mA, Up<2,5	2b	USA, Mot	—
2N3439(L,S)	Si-N	S/Vid, 450/350V, 1A, 1W	2a	USA,EUR	BUX55, BUY59..80, 2N5095
2N344	Ge-P	HF, 5V, 5mA, 0,02W, 50MHz	37d	Csr,Spr	AF124..127, AF200
2N3440(L,S)	Si-N	=2N3439: 300/250V	2a	USA,EUR	BSS46..49, BUX55, BUY59..80, 2N5092
2N3441	Si-N	NF/S-L, 180V, 3A, 25W, >0,8MHz	22a	USA,EUR	BD241D, BD243D, 2SD386(A)
2N3441X	Si-N	=2N3441: -/80V	22a		BD241B, BD537, BD539B, BD951, ++
2N3441Y	Si-N	=2N3441: -/100V	22a		BD241C, BD539C, BD953, 2SD712, ++
2N3442	Si-N	NF/S-L, 180V, 10A, 117W, >0,8MHz	23a	USA,EUR	BD245D, BDX11, 2N3773, 2SD1047, ++
2N3443	Ge-P	HF, 20V, 0,1A, 0,3W, >75MHz	2a	Cen	2N3323..25
2N3444(S)	Si-N	S, 80V, 1A, 1W, >175MHz, <50/70ns	2a	USA,Mic,Mot	BSV95, 2N3735, 2SC1069
2N3444(S)	Si-N			Sgs,Tix,++	—
2N3445	Si-N	NF/S-L, 80V, 7,5A, 115W, 16MHz, B>20	23a	USA, Mot	BD245B, BDV93, BDX93, 2N5874, ++
2N3448	Si-N	=2N3445: 100V	23a	USA, Mot	BD245C, BDV95, BDX95, 2N563233, ++
2N3447	Si-N	=2N3445: B>40	23a	USA, Mot	BD245B, BDV93, BDX93, 2N5874, ++
2N3448	Si-N	=2N3445: 100V, B>40	23a	USA, TIX	BD245C, BDV95, BDX95, 2N5632..35, ++
2N3449	Ge-P	S, 15V, 0,1A, 0,15W, >300MHz	2a	Idi,Ssi,Sty	2N705A, 2N964(A), 2N2635, 2N2955..57
2N345	Ge-P	HF, 5V, 5mA, 0,02W, 50MHz	37d	Csr,Spr	AF124..127, AF200
2N3450	Si-N	S, 120V, 0,8A, 0,6W, <100/235ns	2a	Ray,Sty	2N2102, 2N2405, 2N3019..20, 2SC2106
2N3451	Si-P	S, 6V, 0,3W, >300MHz, <35/32ns	2a	Idi,Mic,Nsc	BSX36

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2N3452	N-FET	Uni, 50V, Idss>0,8mA, Up<9,8	5k	USA,Tix	2N3365
2N3453	N-FET	Uni, 50V, Idss>0,2mA, Up<4,8	5k	USA,TIX	2SK40, 2SK48, 2SK59
2N3454	N-FET	Uni, 50V, Idss>0,05mA, Up<2,3	5k	USA,Tix	2N3367, 2N3370, 2N4118
2N3455	N-FET	Uni, 50V, Idss>0,8mA, Up<9,8	5k	USA,Tix	2N3365
2N3458	N-FET	Uni, 50V, Idss>0,2mA, Up<4,8	5k	USA,Tix	2SK40, 2SK46, 2SK59
2N3457	N-FET	Uni, 50V, Idss>0,05mA, Up<2,3	5k	USA,Tix	2N3367, 2N3370, 2N4118
2N3458	N-FET	Uni, ra, 50V, Idss>3mA, Up<8	2b	USA,Mot,Tix	BF244A, BF245A, 2N3819, 2N3823, ++
2N3459	N-FET	Uni, ra, 50V, Idss>0,8mA, Up<4	2b	USA,Mot,Tix	2N5359
2N348	Ge-P	HF, 5V, 5mA, 0,02W, 75MHz	37d	Csr,Spr	AF124..125, AF200
2N3460	N-FET	Uni, ra, 50V, Idss>0,2mA, Up<2	2b	USA,Mot,Tix	2N3367, 2N3370, 2N4118
2N3461	Ge-P	NF-Tr, 60V, 3A, 5W(Tc=25°)	2a	Can,Gpd	2N1039..41, 2N2565..67
2N3462	Si-N	Uni, 50V, 0,03A, 0,3W, >10MHz	2a	Amp	BC187, BC182, BC237, BC547, ++
2N3463	Si-N	Uni, 60V, 0,03A, 0,3W, >45MHz	2a	Amp	BC174, BC182, BC190, BC546, ++
2N3464	Si-N	NF/S, 60V, 5A, 5W(Tc=25°), >30MHz	2a	Csr,Ssi,Tiw	BFT32..34, BSS45, 2N5336..39
2N3465	N-FET	Uni, 40V, Idss>1mA, Up<10	2f	Tdy	—
2N3466	N-FET	Uni, 40V, Idss>1mA, Up<10	2f	Tdy	—
2N3467(S)	Si-P	S, 40V, 1A, 1W, >175MHz, B>40	2a	USA,Mot,Tix	2SA717, 2SA799
2N3468(S)	Si-P	=2N3467: 50V, >150MHz, B>25	2a	USA,Mot,Tix	2SA717, 2SA799
2N3469	Si-N	NF/S, 35V, 5A, 1,2W, >20MHz	2a	USA,TIx	BFT32..34, BSS45, 2N5336..39
2N347(A)	Si-N	NF/S, 60V, 0,06A, 0,75W, 3MHz	49m	Bog	(BD517, BD519, BD525, BD527, ++)
2N3470	Si-N	S-L, 50V, 10A, 150W, B>100	49m	USA,Whs	—
2N3471	Si-N	=2N3470: 100V	49m	USA,Whs	—
2N3472	Si-N	=2N3470: 150V	49m	USA,Whs	—
2N3473	Si-N	=2N3470: 200V	49m	USA,Whs	—
2N3474	Si-N	S-L, 50V, 10A, 150W, B>350	49m	USA,Whs	—
2N3475	Si-N	=2N3474: 100V	49m	USA,Whs	—
2N3476	Si-N	=2N3474: 150V	49m	USA,Whs	—
2N3477	Si-N	=2N3474: 200V	49m	USA,Whs	—
2N3478	Si-N	VHF/UHF, ra, 30V, 0,2W, 900MHz	5g	USA,Mic,Rca	BF377..378, BF689, BF763, 2N2857, ++
2N3479...3481	UJT-P	Ip<20µA, Iv>4mA	5e	The	—
2N348(A)	Si-N	NF/S, 90V, 0,05A, 0,75W, 3MHz	49m	Bog	(BD139, BD389, BD529, BD829, ++)
2N3482	UJT-P	=2N3479: Ip<2µA	5e		2N4852, 2N4892
2N3483	UJT-P	=2N3479: Ip<5µA	5e		2N2646, 2N4871
2N3484	UJT-P	=2N3479: Ip<5µA	5a		2N2646, 2N4871
2N3485(A)	Si-P	=2N2906(A): 0,4W	2a	USA,Mot,Tix	→2N2906(A)
2N3486(A)	Si-P	=2N2907(A): 0,4W	2a	USA,Mot,Tix	→2N2907(A)
2N3487	Si-N	S-L, 60V, 7,5A, 117W, B>20	49m	USA,Mot,Tix	2N5288..89
2N3488	Si-N	=2N3466: 100V	49m	USA,Mot,Tix	2N5288..89
2N3489	Si-N	=2N3488: 120V, B>15	49m	USA,Mot,Tix	2N5288..89
2N349(A)	Si-N	NF/S, 125V, 0,05A, 0,75W, 3MHz	49m	Bog	(BD424, BF457, BF857, 2SC2384, ++)
2N3490	Si-N	S-L, 60V, 7,5A, 117W, B>40	49m	USA,Mot,Tix	2N5288..89
2N3491	Si-N	=2N3490: 100V	49m	USA,Mot,Tix	2N5288..89
2N3492	Si-N	=2N3490: 120V, B>30	49m	USA,Mot,Tix	2N5266..89
2N3493	Si-N	VHF, 12V, 0,025A, 0,15W, >400MHz	5g	Etc,Sca,SSi	BF377..378, BF689, BF783, 2N2857, ++
2N3494(S)	Si-P	Uni, 60V, 0,1A, 0,6W, >200MHz	2a	USA,Mot,Tix	BC303, BSV17, 2SA606
2N3495(S)	Si-P	=2N3494: 120V, >150MHz	2a	USA,Mot,Tix	2N3834..37, 2SA712
2N3496	Si-P	=2N3494: 0,4W	2a	USA,Mot,Tix	BC558, 2SA970, 2SA1049, 2SA1285(A), ++
2N3497	Si-P	=2N3495: 0,4W	2a	USA,Mot,Tix	BF398, 2SA970, 2SA1049, 2SA12S5(A), ++
2N3498(S)	Si-N	Uni, 100V, 0,5A, 1W, >150MHz, B>40	2a	USA,Mic,Mot	BC141, BC300, BSW39, 2N1990, ++
2N3499(S)	Si-N	=2N3498: B>100	2a	USA,Mic,Mot	BC141, BC300, BSW39, 2N1990, ++
2N35	Ge-N	NF/S, 30V, 300mA, 0,05W	2a	USA	(AC127, ASY28..29)
2N35/5	Ge-N	NF/S, 40V, 0,1A, 0,15W	2a	Syl	(AC127, ASY28)
2N350	Ge-P	NF/S-L, 40V, 3A, 10W(Tc=75°)	23a	USA, Mot	AD149, AUY19..20, 2N2143..46, ++
2N3500(S)	Si-N	=2N3498: 150V, 0,3A	2a	USA,Mic,Mot	BSS43, BSW88, 2SC1860
2N3501(S)	Si-N	=2N3498 150V, 0,3A, B>100	2a	USA,Mic,Mot	BSS43, BSW66, 2SC18+F1266860
2N3502	Si-P	Uni, ra, 45V, 0,6A, 0,7W, <60/120ns	2a	USA,Sgs,Tix	BC181, BC303..304, 2N3468, 2SA717, ++
2N3503	Si-P	=2N3502: 60V	2a	USA,Sgs,Tix	BC161, BC303..304, 2SA717, 2SA742, ++
2N3504	Si-P	=2N3502: 0,4W	2a	USA,Sgs,Tix	BC416, BC560, BSW24, 2N2906..07(A), +
2N3505	Si-P	=2N3502: 60V, 0,4W	2a	USA,Sgs,Tix	BC418, BC560, BSW24, 2N2906..07(A), +
2N3506(S)	Si-N	S, 60V, 3A, 1W, <45/90ns	2a	USA,Mot,Tix	—
2N3507(S)	Si-N	=2N3506: 80V	2a	USA,Mot,Tix	—
2N3508	Si-N	SS, 40V, 0,5A, 0,4W, <12/18ns, B>40	2a	Mot,Sca,SSi	BSS10, BSX28, BSX39, 2N3261
2N3509	Si-N	=2N3508: B>100	2a	Mot,Sca,SSi	BSS10, BSX26, BSX39, 2N3261
2N350A	Ge-P	=2N350: 50V, 5A, 90W	23a		AL102..103, AUY21..22, 2N1545..48, ++
2N351	Ge-P	NF/S-L, 40V, 3A, 10W(Tc=75°)	23a	USA, Mot	AD149, AUY19..20, 2N2143..48, ++
2N3510	Si-N	SS, 40V, 0,5A, 0,38W, <20/25ns	2a	Fch,Mot,++	BSS10, BSX26, BSX39, 2N3261

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2N3511	Si-N	SS, 40V, 0,5A, 0,36W, <16/18ns	2a	Fch,Mot,++	BSS10, BSX26, BSX39, 2N3261
2N3512	Si-N	S, 60V, 1A, 0,8W, <30/45ns	2a	Fer,Rca,++	BSS27, BSV77, BSV95, 2N5189, ++
2N3513	Si-N	Dual, 60V, 0,5A, 0,3W, >50MHz	TO-71	Gen	(BFX70..72, 2N2060, 2N2223)
2N3514	Si-N	=2N3513: 0,35W		Gen	—
2N3515	Si-N	=2N3513: 0,35W	10-FLP	Gen,Mot	—
2N3516	Si-N	Dual, 100V, 0,5A, 0,3W, >50MHz	TO-71	Gen	(BFX70..72, 2N2060, 2N2223)
2N3517	Si-N	=2N3514: 0,35W		Gen	—
2N3518	Si-N	=2N3514: 0,35W	10-FLP	Gen,Mot	—
2N3519	Si-N	Dual, 60V, 0,05A, 0,35W, >30MHz		Gen	—
2N351A	Ge-P	=2N351: 50V, 5A, 90W	23a		AL102..103, AUY21..22, 2N1545..48, ++
2N352	Ge-P	NF/S-L, -/40V, 2A, 25W	≈23	Phc,Lte	AD149, AUY19..20, 2N2143..46, ++
2N3520	Si-N	=2N3519:	10-FLP	Gen	—
2N3521	Si-N	Dual, 70V, 0,05A, 0,6W, >30MHz	TO-77	Gen	BFX70..72, 2N2060, 2N2223
2N3522	Si-N	=2N3521: 0,3W	TO-71	Gen	(BFX70..72, 2N2060, 2N2223)
2N3523	Si-N	=2N3521: 0,35W		Gen	—
2N3524	Si-N	=2N3521: 0,35W	10-FLP	Gen	—
2N3525	50Hz-Thy	=2N3228: 400V	22a	Rca,Sgs,Tag	2N4101, BStC0526L, TAG671-400, TAG676-400
2N3526	Si-N	Nix, 130V, 0,8W, >40MHz	2a	Fch,Idi,Sca	BF257..259, BF657..659, 2N5058..59, ++
2N3527	Si-P	NF, 30V, 0,1A, 0,4W, >5MHz	2a	Sca,Tdy	BC213, BC258, BC308, BC558, ++
2N353	Ge-P	NF/S-L, -/40V, 2A, 30W	≈23	Phc,Lte	AD149, AUY19..20, 2N2143..46, ++
2N354	Si-P	HF/S, 25V, 0,05A, 0,15W	37d	Phc	BC213, BC258, BC308, BC558, ++
2N3543	Si-N	HF/S-L, 65V, 5A, PQ=20W(50MHz)	23a	Itt,Trw,++	—
2N3544	Si-N	VHF/UHF-O, 25V, 0,1A, PQ=16mW(1GHz)	2a	USA,Mot	BFX59
2N3545	Si-P	Uni, 20V, 0,2A, 0,36W, <60/90ns	2a	USA,Mic,Nsc	BC308, BC558, BSW24, 2N2906..07(A), ++
2N3546	Si-P	S, 15V, 0,2A, 0,36W, <25/35ns	2a	USA,Mic,Mot	BSX36
2N3547	Si-P	Uni, 60V, 0,1A, 0,4W, >45MHz	2a	Mic,Nsc,++	BC212, BC258, BC266, BC556, ++
2N3548	Si-P	Uni, 60V, 0,1A, 0,4W, >60MHz	2a	Mic,Nsc,++	BC212, BC256, BC266, BC556, ++
2N3549	Si-P	Uni, 60V, 0,1A, 0,4W, >60MHz	2a	Mic,Nsc,++	BC212, BC258, BC266, BC556, ++
2N355	Si-P	HF/S, 10V, 0,05A, 0,15W	37d	Phc	BC213, BC258, BC308, BC556, ++
2N3550	Si-P	Uni, 60V, 0,1A, 0,4W, >60MHz	2a	Mic,Nsc,++	BC212, BC256, BC266, BC556, ++
2N3551	Si-N	S-L, 115V, 12A, 40W, >40MHz		USA,Tix	—
2N3552	Si-N	=2N3551: 140V		USA,Tix	—
2N3553	Si-N	VHF-O/Tr, 65V, 1A, PQ=2,5W(175MHz)	2a	USA,EUR	BFW47, BFS23, BLY34, 2SC2419
2N3554	Si-N	S, 60V, 1,2A, 0,8W, <50/105ns	2a	Sca,Sem,Tix	BSS14, 2N3734..35, 2N5262
2N3555	50Hz-Thy	30V, 1A(Tc=100°), Igt/Ih<0,02/<3mA	2a	Tag,Tix	2N2323A
2N3556	50Hz-Thy	=2N3555: 60V	2a		2N2324A
2N3557	50Hz-Thy	=2N3555: 100V	2a		2N2324A
2N3558	50Hz-Thy	=2N3555: 200V	2a		2N2326A
2N3559	50Hz-Thy	=2N3555: Igt/Ih<0,2/<5mA	2a		2N2323, 2N6333, TAG615-100, (MCR606-2)
2N356(A)	Ge-N	S, 20..30V, 0,5A(ss), 0,1..0,15W	2a	USA	ASY26..29, ASY73..75
2N3560	50Hz-Thy	=2N3556: Igt/Ih<0,2/<5mA	2a		2N2324, 2N6334, TAG615-100, (MCR606-3)
2N3561	50Hz-Thy	=2N3557: Igt/Ih<0,2/<5mA	2a		2N2324, 2N6334, TAG615-100, (MCR606-3)
2N3562	50Hz-Thy	=2N3558: Igt/Ih<0,2/<5mA	2a		2N2326, 2N6335, TAG615-200, (MCR606-4)
2N3563	Si-N	UHF/ZF, 30V, 0,05A, 0,2W, >600MHz	8a	USA,Mic,Sgs	BF377..378, BF689, BF763, 2N2857, ++
2N3564	Si-N	VHF/ZF, 30V, 0,05A, 0,2W, >600MHz	8a	USA,Mic,Sgs	BF370, BF920..921(S), BF959
2N3565	Si-N	Uni, 30V, 0,05A, 0,2W, >40MHz	8a	USA,Mic,Sgs	BC166, BC163, BC238, BC548, ++
2N3566	Si-N	Uni, 40V, 0,2A, 0,3W, >40MHz	8a	USA,Mic,Sgs	BC167, BC182, BC237, BC547, ++
2N3567	Si-N	Uni, 80/40V, 0,5A, 0,3W, >60MHz, B>40	8a	USA,Mic,Sgs	BC639, BCX24, 2N3700..01, 2SD667, ++
2N3568	Si-N	=2N3587: 80/60V	8a	USA,Mic,Sgs	BC639, BCX24, 2N3700..01, 2SD667, ++
2N3569	Si-N	=2N3567: B>100	8a	USA,Mic,Sgs	BC639, BCX24, 2N3700..01, 2SD667, ++
2N357(A)	Ge-N	S, 20..30V, 0,5A(ss), 0,1..0,15W	2a	USA	ASY28..29, ASY73..75
2N3570	Si-N	VHF/UHF, ra, 30V, 0,05A, 1700MHz	5g	USA,EUR	BFR37, BFW30, BFX58, BFX73
2N3571	Si-N	VHF/UHF, ra, 30V, 0,05A, 1400MHz	5g	USA,EUR	BFR37, BFW30, BFX59, BFX73
2N3572	Si-N	VHF/UHF, ra, 30V, 0,05A, 1200MHz	5g	USA,EUR	BFR37, BFW30, BFX59, BFX73
2N3573	P-FET	Uni, 25V, Idss>0,02mA, Up<2V	5n	Tix	2N5471
2N3574	P-FET	Uni, 25V, Idss>0,075mA, Up<2V	5n	Tix	2N2841..42, 2N5472
2N3575	P-FET	Uni, 25V, Idss>0,2mA, Up<4V	5n	Tix	2N2643
2N3576	Si-P	S, 20V, 0,2A, 0,36W, <30/50ns	2a	USA,Mic,Tix	BSX36
2N3577	Si-N	S-L, 100V, 2A, 85W, >10MHz		Tix	2N1722..23, (2SC2681, 2SC2706, 2SC2637)
2N3578	P-FET	Uni, 20V, Idss>0,9mA, Up<4V	2a	Isi,Six,Tix	2N2606, 2N5266
2N3579	Si-P	Uni, 60V, 0,03A, 0,4W, >80MHz, B>30	2a	Sca,Sem,SSi	BC212, BC256, BC266, BC558, ++
2N358(A)	Ge-N	S, 20..30V, 0,5A(ss), 0,1..0,15W	2a	USA	ASY28..29, ASY73..75
2N3580	Si-P	=2N3579: B>60	2a	Sca,Sem,Ssi	BC212, BC256, BC266, BC556, ++
2N3581	Si-P	Uni, 50V, 0,03A, 0,4W, >30MHz, B>50	2a	Sca,Sem,Ssi	BC212, BC257, BC307, BC557, ++
2N3582	Si-P	=2N3581: B>100	2a	Sca,Sem,Ssi	BC212, BC257, BC307, BC557, ++
2N3583	Si-N	S-L, 250/175V, 2A, 35W, >10MHz	22a	Mot,Tho,++	BUX84, TIP75(A..C), 2N4240, 2SC3169, ++

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2N3584	Si-N	=2N3583: 375/250V	22a	Mot,Tho,++	BUX84, TIP75A..C, 2N4240, 2SC3169,++
2N3585	Si-N	=2N3583: 500/300V	22a	Mot,Tho,++	BUX84, TIP75C, 2N4240, 2SC3169,++
2N3586	Si-P	Dual, Chopper, 45V, 0,1A, 0,25W		Nsc	—
2N3587	Si-N	Dual, 60V, 0,5A, >80MHz	TO-77	Mic,Nsc,Sgs	BFX70..72, 2N2060, 2N2223
2N3588	Ge-P	VHF, 25V, 10mA, 0,1W, >200MHz	5g	Phi,Ssi	AF108, AF109R, AF306, 2N3323..25
2N3589	Si-N	S-L, 200V, 0,5A, >15MHz, B>30	43m	USA	(BF488..468, BF757..759, MJE340,++)
2N359	Ge-P	NF/S, 25V, 0,4A, 0,17W	2a	USA	AC128, AC152..153, AC188
2N3590	Si-N	=2N3589: B>75	43m	USA	(BF468..488, BF757..759, MJE340,++)
2N3591	Si-N	=2N3569:	5g	USA	(BF466..488, BF757..759, MJE340,++)
2N3592	Si-N	=2N3589: B>75	5g	USA	(BF488..468, BF757..759, MJE340,++)
2N3593	Si-N	=2N3569:	49m	USA	(BF488..488, BF757..759, MJE340,++)
2N3594	Si-N	=2N3569: B>75	49m	USA	(BF488..468, BF757..759, MJE340,++)
2N3595	Si-N	=2N3569:	49m	USA	(BF488..488, BF757..759, MJE340,++)
2N3596	Si-N	=2N3589: B>75	49m	USA	(BF488..468, BF757..759, MJE340,++)
2N3597	Si-N	S-L, 60/40V, 20A, 100W(Tc=100°)	49m	USA,Tix	2N2815..22, 2N5539
2N3596	Si-N	=2N3597: 80/60V	49m	USA,Tix	2N2815..22, 2N5539
2N3599	Si-N	=2N3597: 100/80V	49m	USA,Tix	2N2816..18, 2N2820..22, 2N5539
2N36	Ge-P	NF/HF, 20V, 500mA, 0,05W	3a	USA	(AC125..128, AC151, ASY28..27)
2N360	Ge-P	NF/S, 32V, 0,4A, 0,17W	2a	USA	AC128, AC152..153
2N3600	Si-N	VHF, ra, 30V, 0,05A, 0,2W, >850MHz	5g	USA,EUR	BF377..378, BF689, BF783, 2N2857,++
2N3601	Ge-P	NF/S, 100V, 3,5A, 0,5W, >20MHz	2a	Sty,Tix	—
2N3602	Ge-P	NF/S, 100V, 3,5A, 0,75W, >20MHz	49a	Sty,Tix	—
2N3603	Ge-P	NF/S, 130V, 3,5A, 0,5W, >20MHz	2a	Sty,Tix	—
2N3604	Ge-P	NF/S, 130V, 3,5A, 0,75W, >20MHz	49a	Sty,Tix	—
2N3605	Si-N	S, 18V, 0,2A, 0,2W, >300MHz, <35/45ns	7c	Nsc,Tho,++	BSS10..11, BSX19..20, 2N2368..69(A),++
2N3605A	Si-N	=2N3605: 40V	7c		BSS10..11, BSX19..20, 2N2368..69(A),++
2N3608	Si-N	=2N3605 <40/60ns	7c	Nsc,Tho,++	BSS10..11, BSX19..20, 2N2368..69(A)
2N3606A	Si-N	=2N3605 40V, <40/80ns	7c		BSS10..11, BSX19..20, 2N2368..69(A)
2N3607	Si-N	=2N3605 <45/70ns	7c	Nsc,Tho,++	BSS10..11, BSX19..20, 2N2368..69(A)
2N3608	MOS-P-FET-e	S, 25V, Idss<7mA, Up<6V	5(DGSsub)	Dio,Gie	—
2N3609	MOS-P-FET-e	Dual, 25V, Idss<3,2mA, Up<6V	TO-77	Dio,Gie	—
2N361	Ge-P	NF/S, 32V, 0,4A, 0,17W	2a	USA	AC128, AC152..153
2N3610	MOS-P-FET-e	S, 20V, Idss<0,6mA, Up<7V	5(DGSsub)	Dio,Gie	—
2N3611	Ge-P	NF/S-L, 40V, 7A, 77W, B>35	23a	USA, Mot	AL102..103, AUY22, 2N2288..93,++
2N3612	Ge-P	=2N3611: 60V	23a	USA, Mot	AL102..103, AUY22, 2N2292..93,++
2N3613	Ge-P	=2N3611: B>60	23a	USA, Mot	AL102..103, AUY22, 2N2288..93,++
2N3614	Ge-P	=2N3611: 60V, B>60	23a	USA, Mot	AL102..103, AUY22, 2N2292..93,++
2N3615	Ge-P	NF/S-L, 60V, 7A, 77W, B>30	23a	USA, Mot	AL102..103, AUY22, 2N2292..93,++
2N3618	Ge-P	=2N3615: 100V	23a	USA, Mot	AL102..103, 2N2290, 2N2293
2N3617	Ge-P	=2N3615: B>45	23a	USA, Mot	AL102..103, AUY22, 2N2292..93,++
2N3618	Ge-P	=2N3815: 100V, B>45	23a	USA, Mot	AL102..103, 2N2290, 2N2293
2N3619	Si-N	S-L, 75V, 2,5A, 7,5W(Tc=25°), >200MHz	2a	Sca,Sol,Ssi	BSS15, BSV84, BSX84, 2N5320
2N362	Ge-P	NF/S, 25V, 0,2A, 0,17W	2a	USA	AC128, AC152..153, AC188
2N3620	Si-N	S-L, 75V, 5A, 7,5W, >200MHz	≈49m	Sca,Sol,Ssi	—
2N3621	Si-N	S-L, 75V, 10A, 30W, >200MHz	49a	Sca,Sol,Ssi	—
2N3622	Si-N	S-L, 75V, 10A, 30W, >200MHz	49m	Sca,Sol,Ssi	—
2N3623	Si-N	S-L, 75V, 2,5A, 7,5W(Tc=25°), >200MHz	2a	Sca,Sol,Ssi	BSS15, BSV84, BSX84, 2N5320
2N3624	Si-N	S-L, 75V, 5A, 7,5W, >200MHz	≈49m	Sca,Sol,Ssi	—
2N3625	Si-N	S-L, 75V, 10A, 30W, >200MHz	49a	Sca,Sol,Ssi	—
2N3628	Si-N	S-L, 75V, 10A, 30W, >200MHz	49m	Sca,Sol,Ssi	—
2N3627	Si-N	S-L, 100V, 2,5A, 7,5W(Tc=25°), >200MHz	2a	Sca,Sol,Ssi	BSS15, BSV84, BSX84, 2N5320
2N3628	Si-N	S-L, 100V, 5A, 7,5W, >200MHz	≈49m	Sca,Sol,Ssi	—
2N3629	Si-N	S-L, 100V, 10A, 30W, >200MHz	49a	Sca,Sol,Ssi	—
2N363	Ge-P	NF/S, 32V, 0,2A, 0,17W	2a	USA	AC128, AC152..153
2N3630	Si-N	S-L, 100V, 10A, 30W, >200MHz	49m	Sca,Sol,Ssi	—
2N3631	MOS-N-FET-d	Uni, 20V, Idss>2mA, Up<6V	2a	Six	2N3797
2N3632	Si-N	VHF-L, 85V, 3A, PQ=13,5W(175MHz)	49a	USA,EUR	—
2N3633	Si-N	SS, 15V, 0,05A, 0,3W, <9/9ns	2e	USA	BSV89..92, BSX27, BSX44, 2N2475,++
2N3634(S)	Si-P	NF/S, 140V, 1A, 1W, >150MHz, B>50	2a	USA,Mot,Tix	BFT19A,B, BFT28(A..C), 2N5415
2N3635(S)	Si-P	=2N3634: B>100	2a	USA,Mot,Tix	BFT19A,B, BFT28(A..C), 2N5415
2N3636(S)	Si-P	=2N3634: 175V	2a	USA,Mot,Tix	BFT19A,B, BFT28A..C, 2N5415
2N3637(S)	Si-P	=2N3634: 175V, B>100	2a	USA,Mot,Tix	BFT19A,B, BFT28A..C, 2N5415
2N3636(A)	Si-P	NF/S, 25V, 0,5A, 0,3W, <90/170ns	8a	Fch,Nsc,Sgs	BC160..161, BC303..304, 2N3072..73,++
2N3639	Si-P	S, 6V, 0,08A, 0,2W, <30/32ns	8a	Fch,Nsc,Sgs	BSX36
2N364	Ge-N	NF/S, 18V, 0,25A, 0,15W, 2,5MHz	2a	Csr,Etc	AC127, ASY28, ASY73..75
2N3640	Si-P	=2N3639: 12V	8a	Fch,Nsc,Sgs	BSX36

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2N3641	Si-N	NF/S, 60/30V, 0,5A, 0,35W, >250MHz, B>40	8a	Fch,Nsc,Sgs	BC337A, BC637, BC639, 2N3299..3300,++
2N3642	Si-N	=2N3641: 60/45V	8a	Fch,Nsc,Sgs	BC337A, BC637, BC639, 2N3299..3300,++
2N3643	Si-N	=2N3641: B>100	8a	Fch,Nsc,Sgs	BC337A, BC637, BC639, 2N3299..3300,++
2N3644	Si-P	NF/S, 45V, 0,5A, 0,3W, >200MHz	8a	Fch,Nsc,Sgs	BC327, BC638, BC640, 2N3072..73,++
2N3645	Si-P	=2N3644: 60V	8a	Fch,Nsc,Sgs	BC327A, BC638, BC640, 2N3072..73,++
2N3646	Si-N	S, 40V, 0,2A, 0,2W, <25/35ns	8a	Fch,Nsc,Sgs	BSS+F1309910..11, BSX19..20, 2N2368..69(A),++
2N3647	Si-N	=2N3510: 0,4W	2a	USA,Mot,Sgs	→2N3510
2N3648	Si-N	=2N3511: 0,4W	2a	USA,Mot,Sgs	→2N3511
2N3649	F-Thy	50V, 25A(Tc=40°)Igt/Ih<180/<150mA, <15µs	21b	USA,Tag,Tho	BTW28/500R, CS15,9-04
2N365	Ge-N	NF/S, 18V, 0,25A, 0,15W, 3MHz	2a	Csr,Etc	AC127, ASY28, ASY73..75
2N3650	F-Thy	=2N3649: 100V	21b		BTW28/500R, CS15,9-04
2N3651	F-Thy	=2N3649: 200V	21b		BTW28/500R, CS15,9-04
2N3652	F-Thy	=2N3649: 300V	21b		BTW28/500R, CS15,9-04
2N3653	F-Thy	=2N3649: 400V	21b		BTW28/500R, CS15,9-04
2N3654	F-Thy	=2N3649: <10µs	21b		BTW28/500R, CS15,9-04
2N3655	F-Thy	=2N3650: <10µs	21b		BTW28/500R, CS15,9-04
2N3656	F-Thy	=2N3651: <10µs	21b		BTW28/500R, CS15,9-04
2N3657	F-Thy	=2N3652: <10µs	21b		BTW28/500R, CS15,9-04
2N3658	F-Thy	=2N3653: <10µs	21b		BTW28/500R, CS15,9-04
2N3659	Si-N	S/Vid, 220V, 0,5A, 4W(Tc=25°), >50MHz	2a	USA	BSS48..40, 2N3440, 2SD578
2N366	Ge-N	NF/S, 18V, 0,25A, 0,15W, 3,5MHz	2a	Csr,Etc	AC127, ASY28, ASY73..75
2N3660	Si-P	Uni, 40V, 1,5A, 5W(Tc=25°), >25MHz	2a	USA	BC461, BCX60, BSV17, 2N5322..23,++
2N3661	Si-P	=2N3660: 60V	2a	USA	BC461, BCX60, BSV17, 2N5322..23,++
2N3662	Si-N	VHF/ZF, 18V, 0,025A, 0,2W, 1000MHz	7c	Gen,Nsc,Sem	BF225, BF314, BF502, BF505, BF507++
2N3663	Si-N	VHF/ZF, 30V, 0,025A, 0,2W, 1000MHz	7c	Gen,Nsc,Sem	BF225, BF314, BF502, BF505, BF507++
2N3664	Si-N	HF/UHF-E, 60V, 0,5A, PQ>2,2W(250MHz)	49a	Mot,Sca	—
2N3665	Si-N	NF/S, 120V, 1A, 0,3W, >60MHz, B>40	2a	USA,Nsc,Tix	BSS42..43, 2N2102, 2N2405, 2N3019..20++
2N3666	Si-N	=2N3665: B>100	2a	USA,Nsc,Tix	BSS42..43, 2N2102, 2N2405, 2N3019..20++
2N3667	Si-N	S-L, 50V, 15A, 117W, >0,5MHz	23a	USA	BD315, BD745, BDX13, 2N3055,++
2N3668	50Hz-Thy	100V, 8A(Tc=80°), Igt/Ih<40/<50mA	23a	Rca	2N2575
2N3669	50Hz-Thy	=2N3668: 200V	23a		2N2578
2N367	Ge-P	NF/S, 18V, 0,3A, 0,1W	2a	Csr,Etc	AC125..126, AC151, ASY26
2N3670	50Hz-Thy	=2N3668: 400V	23a		2N2578
2N3671	Si-P	S, 60V, 0,6A, 0,6W, 35/80ns	2a	USA,Fch	2SA717, 2SA742
2N3672	Si-P	=2N3671: 0,4W	2a	USA,Fch	BSW24, 2N2906..07(A)
2N3673	Si-P	=2N3671: 0,35W	2a	USA,Fch,Mot	BSW24, 2N2906..07(A)
2N3675	Si-N	S, 90/55V, 3A, 8,8W(Tc=25°), >1MHz	2a	USA,Tix	BSX64, BUY41, 2N4239, 2SC2214,++
2N3676	Si-N	=2N3675: 90/90V	2a	USA,Tix	BSX64, BUY41, 2N4239, 2SC2214,++
2N3677	Si-P	Chopper, 30/20/30V, 0,1A, 0,4W, >5MHz	2a	USA,Mot	2N2946
2N3678	Si-N	Uni, 75V, 0,6A, 0,8W, <40/250ns	2a	Fch,Nsc,++	BSW39, BSW53..54, 2N2218..19A, 2N3444
2N3679	UJT-P	Iv>4,2mA	5	Gen	—
2N368	Ge-P	NF/S, 30V, 0,3A, 0,1W	2a	Csr,Etc	AC125..126, AC151, ASY28
2N3680	Si-N	Dual, ra, 60V, 0,03A, 0,6W, >60MHz	TO-77	USA,Sgs,Tix	BFX70..72, 2N2060, 2N2223
2N3681	Si-N	UHF, 10V, 0,025A, 0,2W, >1000MHz	5g	Etc,Sca,SSi	BF377..378, BF669, BF763, 2N2857,++
2N3682	Si-N	SS, 40V, 0,2A, 0,36W, <12/-ns	2a	Tix	BSS10..11, BSX19..20, 2N2366..69(A),++
2N3683	Si-N	UHF, 30V, 0,03A, 0,2W, >1000MHz	5g	USA,Fch	BF377..378, BF669, BF763, 2N2857,++
2N3684(A)	N-FET	Uni, ra, 50V, Idss>2,5mA, Up<5V	5k	Isi,NSC,++	BF256A, BFS71, 2N3822, 2N4221,++
2N3685(A)	N-FET	Uni, ra, 50V, Idss>1mA, Up<3,5V	5k	Isi,NSC,++	BFW12, 2N4340, 2N5484
2N3686(A)	N-FET	Uni, ra, 50V, Idss>0,4mA, Up<2V	5k	Isi,NSC,++	2N4339, 2N5358, 2SK83, 2SK193, 2SK195,++
2N3687(A)	N-FET	Uni, ra, 50V, Idss>0,1mA, Up<1,2V	5k	Isi,NSC,++	2N4117, 2SK92..93, 2SK103
2N3688	Si-N	VHF/ZF, re, 40V, 0,03A, 0,2W, >400MHz	8a	Fch,Sgs	BF198, BF225, BF310, BF367, BF596++
2N3689	Si-N	VHF/ZF, re, 40V, 0,03A, 0,2W, >400MHz	8a	Fch,Sgs	BF198, BF225, BF310, BF367, BF596++
2N369	Ge-P	NF/S, 30V, 0,3A, 0,1W	2a	Csr,Etc	AC125..126, AC151, ASY26
2N3690	Si-N	VHF/ZF, ra, 40V, 0,03A, 0,2W, >400MHz	8a	Fch,Sgs	BF198, BF225, BF310, BF367, BF596++
2N3691	Si-N	HF, 35V, 0,05A, 0,2W, 260MHz	8a	USA,Mic,Sgs	BF240..241, BF254..255, BF594..595,++
2N3692	Si-N	HF, 35V, 0,05A, 0,2W, 260MHz	8a	USA,Mic,Sgs	BF240..241, BF254..255, BF594..595,++
2N3693	Si-N	FM-ZF, 45V, 0,05A, 0,2W, 400MHz	8a	USA,Mic,Sgs	BF240..241, BF254..255, BF594..595,++
2N3694	Si-N	FM-ZF, 45V, 0,05A, 0,2W, 400MHz	8a	USA,Mic,Sgs	BF240..241, BF254..255, BF594..595,++
2N3695	P-FET	Uni, ra, 30V, Idss>1,75mA, Up<4,5V	5n	Tsc	2N2609
2N3696	P-FET	Uni, ra, 30V, Idss>0,5mA, Up<3,2V	5n	Tsc	—
2N3697	P-FET	Uni, ra, 30V, Idss>0,2mA, Up<1,6V	5n	Tsc	2N2843
2N3698	P-FET	Uni, ra, 30V, Idss>0,05mA, Up<1,1V	5n	Tsc	—
2N37	Ge-P	NF/HF, 15V, 50mA, 0,05W	2a	USA	(AC125..126, AC151, ASY26..27)
2N370	Ge-P	HF, 24V, 10mA, 0,08W, 30MHz	1g	Rca	AF124..127, AF200
2N370/33	Ge-P	=2N370:	5g	Syl	AF124..127, AF200
2N3700	Si-N	Uni, 140V, 1A, 0,5W, 200MHz, B>100	2a	USA,EUR	BSS59, 2SC2383, 2SC3228

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2N3701	Si-N	=2N3700: B>40	2a	USA,EUR	BSS59, 2SC2383, 2SC3228
2N3702	Si-P	Uni, 40V, 0,2A, 0,3W, >100MHz, B>60	7c	USA, Aeg, Tix	BC212, BC257, BC307, BC557, ++
2N3703	Si-P	=2N3702: 45V, B>30	7c	USA, Aeg, Tix	BC212, BC257, BC307, BC557, ++
2N3704	Si-N	Uni, 50V, 0,8A, 0,36W, >100MHz, B>100	7c	USA, Aeg, Tix	BC337, BC637, BC639, 2SD667, ++
2N3705	Si-N	=2N3704: B>50	7c	USA, Aeg, Tix	BC337, BC637, BC639, 2SD667, ++
2N3706	Si-N	=2N3704: 40V, B>30	7c	USA, Aeg, Tix	BC337, BC635, BC637, BC639, ++
2N3707	Si-N	NF-V, ra, 30V, 0,03A, 0,36W, 80MHz	7c	USA, Aeg, Tix	BC169, BC184, BC239, BC549, ++
2N3706	Si-N	NF, 30V, 0,03A, 0,36W, 80MHz, B=45..660	7c	USA, Aeg, Tix	BC168, BC163, BC236, BC549, ++
2N3709	Si-N	=2N3706: B=45..165	7c	USA, Aeg, Tix	BC168, BC163, BC236, BC548, ++
2N371	Ge-P	HF, 24V, 10mA, 0,06W, 30MHz	1g	Rca	AF124..127, AF200
2N371/33	Ge-P	=2N371:	5g	Syl	AF124..127, AF200
2N3710	Si-N	=2N3706: B=90..330	7c	USA, Aeg, Tix	BC168, BC183, BC238, BC548, ++
2N3711	Si-N	=2N3706: B=180..600	7c	USA, Aeg, Tix	BC168, BC183, BC236, BC548, ++
2N3712(S)	Si-N	Vid, 150V, 0,2A, 1W, >40MHz	2a	USA, Mot, Tix	BF257..259, BF657..759, 2N5058..59, ++
2N3713	Si-N	NF/S-L, 60V, 10A, 150W, >4MHz, B>25	23a	USA, Mot, Sgs	BD545B, BD315, 2N3772, 2N5632..34, ++
2N3713	Si-N			Tos, Tix, ++	—
2N3714	Si-N	=2N3713: 100V	23a		BD545C, BD317, 2N3772, 2N5632..34, ++
2N3715	Si-N	=2N3713: B>50	23a		BD545B, BD315, 2N3772, 2N5632..34, ++
2N3716	Si-N	=2N3713: 100V, B>50	23a		BD545C, BD317, 2N3772, 2N5632..34, ++
2N3717	Si-N	HF/S, 80V, 1A, 7,5W(Tc=25°), 250MHz	2a	Mot	2N3553, 2SC2419
2N3718	Si-N	HF/S, 80V, 1A, 10W(Tc=25°), 250MHz	49a	Mot	BLY60
2N3719	Si-P	S, 40V, 3A, 1W, >60MHz, <100/400ns	2a	USA, Mot, Tix	2N3867..68, 2N6303
2N372	Ge-P	HF, 24V, 10mA, 0,06W, 30MHz	1g	Rca	AF124..127, AF200
2N372/33	Ge-P	=2N372:	5g	Syl	AF124..127, AF200
2N3720	Si-P	=2N3719: 60V	2a	USA, Mot, Tix	2N3868, 2N6303
2N3721	Si-N	Uni, 18V, 0,1A, 0,36W, 120MHz	7c	USA, Gen, Mic	BC168, BC183, BC236, BC548, ++
2N3722	Si-N	S, 80V, 0,5A, 0,8W, >300MHz, <62/130ns	2a	USA, Mot	BSV95, 2N3725, 2SC1069
2N3723	Si-N	=2N3722: 100V, <85/160ns	2a	USA, Mot	BSW39, 2SC1069
2N3724	Si-N	S, 50V, 0,5A, 0,6W, >300MHz, 20/55ns	2a	USA, Fer, Itt	BSV77, BSV95, 2N3722..23, 2N5169, ++
2N3724	Si-N			Mot, Sgs, Tix	—
2N3724A	Si-N	=2N3724: 1,2A	2a		BSS14, 2N3734..35, 2N5262
2N3725	Si-N	=2N3724: 80V	2a	=2N3724	BSV95, 2N3722..23, 2SC1069
2N3725A	Si-N	=2N3725: 1,2A	2a		BSS14, 2N3735, 2N5262
2N3726	Si-P	Dual, ra, 45V, 0,3A, 0,5W, >200MHz	TO-77	USA, Fch, Mic	2N4015..4016
2N3726	Si-P			Mot, Sgs, ++	—
2N3727	Si-P	Dual, ra, 45V, 0,3A, 0,5W, >200MHz	TO-77	=2N3727	2N4015..4016
2N3726	Si-N	Dual, 60V, 0,5A, 0,45W, >80MHz	TO-77	Fch, Ray, Sca	BFX70..72, 2N2060, 2N2223
2N3726+A13157	Si-N			Sgs	—
2N3729	Si-N	Dual, 80V, 0,5A, 0,45W, >80MHz	TO-77	=2N3726	BFX70..72, 2N2060, 2N2223
2N373	Ge-P	HF, 24V, 10mA, 0,06W, 30MHz	1g	Rca	AF124..127, AF200
2N373/33	Ge-P	=2N373:	5g	Syl	AF124..127, AF200
2N3730	Ge-P	TV-HA/VH, 320V, 3A, 10W(Tc=55°)	23a	Gpd, Rca	AU107, AU113, AU213, 2N5324
2N3731	Ge-P	TV-HA/VH, 320V, 10A(ss), 5W(Tc=55°)	23a	Gpd, Rca	AU106, AU109, AU111..112, 2N5325
2N3732	Ge-P	TV-HA/VA, 320V, 8A, 3W(Tc=55°)	23a	Gpd, Rca	AU106, AU110, AU210
2N3733	Si-N	VHF/UHF-L, 65V, 3A, PQ>10W(400MHz)	49a	USA, EUR	—
2N3734(S)	Si-N	S/Tr, 50V, 1,5A, 1W, >250MHz, <48/80ns	2a		BSS14, 2N5262
2N3735(S)	Si-N	=2N3734: 75V	2a	USA, EUR	BSS14, 2N5262
2N3736	Si-N	=2N3734: 0,5W	2a	USA, EUR	—
2N3737	Si-N	=2N3734: 75V, 0,5W	2a		—
2N3736	Si-N	NF/S-L, 250/225V, 1A, 20W, >10MHz	22a	USA, Mot, Tho	BUW40(A, B), BUX84, 2N4296..97, ++
2N3739	Si-N	=2N3736: 325/300V	22a	USA, Mot, Tho	BUW40(A, B), BUX64, 2N4296..97, ++
2N374	Ge-P	HF, 24V, 10mA, 0,08W, 30MHz	5g	Gen	AF124..127, AF200
2N3740(A)	Si-P	NF/S-L, 80V, 4A, 25W, >4MHz	22a	USA, Fch, Mot	BD244A, BD540A, BDX14, 2N6313..14, ++
2N3740(A)	Si-P			Sgs, Tho, Tix	—
2N3741(A)	Si-P	=2N3740: 80V	22a	=2N3740	BD244B, BD540B, BDX14, 2N6314, ++
2N3742(S)	Si-N	Vid, 300V, 0,05A, 1W, >30MHz	2a	Mot, Nsc, Sca	BF259, BF659, BFR59, BFS89, 2N5058
2N3742(S)	Si-N			Ssi, Stc	—
2N3743(S)	Si-P	Vid, 300V, 0,05A, 1W, >30MHz	2a	Mot, Nsc, Sca	BFT44, BFQ37, 2SB622
2N3743(S)	Si-P			Ssi, Stc	—
2N3744	Si-N	S-L, 60V, 5A, 30W(Tc=100°), >30MHz	50g	USA, Tix	—
2N3745	Si-N	=2N3744: 60V	50g		—
2N3746	Si-N	=2N3744: 100V	50g		—
2N3747	Si-N	S-L, 80V, 5A, 30W(Tc=100°), >40MHz	50g	USA, Tlix	—
2N3746	Si-N	=2N3747: 80V	50g		—
2N3749	Si-N	=2N3747: 100V	50g		—
2N375	Ge-P	NF/S-L, 80V, 3A, 106W	23a	USA, Mot	2N1536..48, 2N1541..43, 2N3615..18, ++

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2N3750	Si-N	S-L, 60V, 5A, 30W(Tc=100°), >50MHz	50g	USA, Tix	—
2N3751	Si-N	=2N3750: 60V	50g		—
2N3752	Si-N	=2N3750: 100V	50g		—
2N376	Ge-P	NF/S-L, 40V, 3A, 90W	23a	USA, Mot	2N1529..48, 2N2138..41, 2N2143..46,++
2N3762(S)	Si-P	S/Tr, 40V, 1,5A, 1W, >180MHz, <43/115ns	2a	USA, Mot	BSV82, 2SA799
2N3763(S)	Si-P	=2N3762: 60V	2a		BSV82, 2SA799
2N3764(A)	Si-P	=2N3762: 0,5W	2a		—
2N3765	Si-P	=2N3762: 60V, 0,5W	2a		—
2N3766	Si-N	NF/S-L, 80V, 4A, 20W, >10MHz	22a	USA, Fch, Mot	BD243B, BD539B, BD951, 2N3054,++
2N3766	Si-N			Sgs, Tix	—
2N3767	Si-N	=2N3766: 100V	22a		BD243C, BD539C, BD953, 2N3054,++
2N376A	Ge-P	=2N376: 50V, 5A	23a		2N1535..38, 2N1545..48, 2N3815..18,++
2N377	Ge-N	S, 25V, 0,2A, 0,15W	2a(B=case)	USA, Tix	ASY28..29, ASY73..75
2N3770	Ge-P	HF, 10V, 0,05A, 0,05W, >100MHz	2a	Spr	AF106, AF109R, AF306, 2N3323..25
2N3771	Si-N	NF/S-L50V, 30A, 150W, >0,2MHz	23a	USA, EUR, Tos	BDX41, BDY29, MJ802, 2SD630..631
2N3772	Si-N	NF/S-L, 100V, 20A, 150W, >0,2MHz	23a	USA, EUR, Tos	BDX40, BDY29, MJ802, 2SD797
2N3773	Si-N	NF/S-L, 160V, 16A, 150W, >0,2MHz	23a	USA, EUR, Tos	BDW32..36, BDX50, MJ15015, 2SC2608
2N3774	Si-P	NF/S, 40V, 1A, 5W(Tc=100°), >1MHz, B>20	2a	USA, Tix	BSS17..18, BSW40, BSV82, 2N5322..23
2N3775	Si-P	=2N3774: 60V	2a		BSS17..18, BSW40, BSV82, 2N5322..23
2N3776	Si-P	=2N3774: 80V	2a		BSS17..18, BSW40, BSV82, 2N5322..23
2N3777	Si-P	=2N3774: 100V	2a		BSS17, BSW40, 2N5322
2N3778	Si-P	=2N3774: B>10	2a	USA, Tix	BSS17..18, BSW40, BSV82, 2N5322..23
2N3779	Si-P	=2N3774: 60V, B>10	2a		BSS17..18, BSW40, BSV82, 2N5322..23
2N377A	Ge-N	=2N377: 40V	2a(B=case)		—
2N378	Ge-P	NF/S-L, 40V, 5A, 106W	23a	USA, Mot	2N1529..38, 2N1539..48, 2N3611..18,++
2N3760	Si-P	=2N3774: 80V, B>10	2a		BSS17..18, BSW40, BSV82, 2N5322..23
2N3781	Si-P	=2N3774: 100V, B>10	2a		BSS17, BSW40, 2N5322
2N3782	Si-P	=2N3774: 3A, B>10	2a	USA, Tix	2N3719..20, 2N3867..68, 2N4234..38
2N3763	Ge-P	UHF, 30V, 0,02A, 0,15W, >800MHz	5g	Mot, Ssi	AF139, AF239(S), 2N3279..66
2N3784	Ge-P	UHF, 30V, 0,02A, 0,15W, >700MHz	5g	Mot, Ssi	AF139, AF239(S), 2N3279..66
2N3785	Ge-P	UHF, 15V, 0,02A, 0,15W, >700MHz	5g	Mot, Ssi	AF139, AF239(S), 2N3279..66
2N3788	Si-N	TV-HA, 400/325V, 2A, 100W	23a	Sol, Ssi, Stc	BU104, BU606, BU608
2N3789	Si-P	NF/S-L, 60V, 10A, 150W, >4MHz, B>25	23a	USA, Mot, Sgs	BD546A, BD316, 2N6029..31, 2N6229..31,++
2N3789	Si-N			Tix, Tos,++	—
2N379	Ge-P	=2N378: 60V	23a	USA, Mot	2N1538..38, 2N1546..48, 2N3815..18,++
2N3790	Si-P	=2N3789: 60V	23a		BD546B, BD318, 2N6029..31, 2N6229..31,++
2N3791	Si-P	=2N3789: B>50	23a		BD546A, BD318, 2N6029..31, 2N6229..31,++
2N3792	Si-P	=2N3789: 60V, B>50	23a		BD546B, BD318, 2N6029..31, 2N6229..31,++
2N3793	Si-N	NF, 40V, 0,3A, 0,25W, 220MHz, B>20	≈40b	USA, Mic, Pih	BC337, BC635, BC637, BC639,++
2N3794	Si-N	=2N3793: 100MHz, B>100	≈40b		BC337, BC635, BC637, BC639,++
2N3795	Si-P	NF/S, 120V, 1A, 5W(Tc=25°), >0,5MHz	2a	Csr, Ssi, Stc	2N3634..37, 2N5415
2N3796	MOS-N-FET-d	NF, 30V, Idss>0,5mA, Up<4V	2a	Mot	—
2N3797	MOS-N-FET-d	NF, 30V, Idss>2mA, Up<7V	2a	Mot	—
2N3798	Si-P	Uni, ra, 60V, 0,05A, 0,38W, B>150	2a	USA, Mot, Tix	2SA872(A), 2SA941..942, 2SA970,++
2N3798A	Si-P	=2N3798: 90V	2a		2SA872(A), 2SA941..942, 2SA970,++
2N3799	Si-P	=2N3798: B>300	2a		2SA872(A), 2SA941..942, 2SA970,++
2N3799A	Si-P	=2N3798: 90V, B>300	2a		2SA872(A), 2SA941..942, 2SA970,++
2N38+A13360(A)	Ge-P	NF/HF, 20V, 8mA, 0,05W	2a	USA	(AC125..128, AC151, ASY26..27)
2N380	Ge-P	=2N378: 80V	23a	USA, Mot	2N1535..38, 2N1545..48, 2N3815..18,++
2N3800	Si-P	Dual, ra, 60V, 0,05A, 0,38W, >100MHz	TO-71	Fch, Mot, Nsc	—
2N3800	Si-N			Ray	—
2N3801	Si-P	Dual, ra, 60V, 0,05A, 0,36W, >100MHz	TO-71		—
2N3802	Si-P	Dual, ra, 60V, 0,05A, 0,38W, >100MHz	TO-71		—
2N3803	Si-P	Dual, ra, 60V, 0,05A, 0,38W, >100MHz	TO-71		—
2N3804(A)	Si-P	Dual, ra, 60V, 0,05A, 0,38W, >100MHz	TO-71		—
2N3805(A)	Si-P	Dual, ra, 60V, 0,05A, 0,36W, >100MHz	TO-71		—
2N3806	Si-P	Dual, ra, 60V, 0,05A, 0,6W, >100MHz	TO-77		2N4015..16
2N3807	Si-P	Dual, ra, 60V, 0,05A, 0,6W, >100MHz,	TO-77		2N4015..16
2N3806	Si-P	Dual, ra, 60V, 0,05A, 0,6W, >100MHz	TO-77		2N4015..16
2N3809	Si-P	Dual, ra, 60V, 0,05A, 0,6W, >100MHz	TO-77		2N4015..16
2N381	Ge-P	NF-Tr, 50V, 0,4A, 0,225W, 3MHz	2a(B=case)	USA, Mot	ASY77, 2N1189..90
2N3810(A)	Si-P	Dual, ra, 60V, 0,05A, 0,6W, >100MHz	TO-77		2N4015..16
2N3812	Si-P	Dual, ra, 60V, 0,05A, 0,6W, >100MHz	TO-77		2N4015..16
2N3812	Si-P	Dual, ra, 60V, 0,05A, 0,35W, >100MHz	10-FLP		—
2N3813	Si-P	Dual, ra, 80V, 0,05A, 0,35W, >100MHz	10-FLP		—
2N3814	Si-P	Dual, ra, 60V, 0,05A, 0,35W, >100MHz	10-FLP		—

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2N3815	Si-P	Dual, ra, 60V, 0,05A, 0,35W, >100MHz	10-FLP		—
2N3816(A)	Si-P	Dual, ra, 60V, 0,05A, 0,35W, >100MHz	10-FLP		—
2N3817(A)	Si-P	Dual, ra, 60V, 0,05A, 0,35W, >100MHz	10-FLP		—
2N3818	Si-N	VHF-L, 60V, 2A, PQ=15W(100MHz)	49a	Mot,Sca,Ssi	BLY35, 2N3832
2N3819	N-FET	Uni/VHF, sym, 25V, Idss>2mA, Up<8V	7a	USA,EUR	BF244..245, BFS72, 2N3823
2N382	Ge-P	=2N381: 4MHz	2a(B=case)		ASY77, 2N1189..90
2N3820	P-FET	Uni, sym, 20V, Idss>0,3mA, Up<8V	7e	USA,Phi,Tix	BF320A, 2N3909
2N3821	N-FET	Uni/V/HF, 50V, Idss>0,5mA, Up<4V	5k	USA,EUR	BFS70, 2N4220, 2SK104, 2SK301
2N3822	N-FET	Uni/VHF, 50V, Idss>2mA, Up<6V	5k	USA,EUR	BFS71, BFS80, BFW11, 2N4416
2N3823	N-FET	VHF, ra, 30V, Idss>4mA, Up<8V	5k	USA,EUR	BF244..245, BFS72
2N3824	N-FET	Chopper, sym, Idss>12mA	5k	USA,EUR	BFS73
2N3825	Si-N	Uni, 30V, 0,1A, 0,25W, >200MHz	7c	Mic,Nsc,Tix	BC168, BC183, BC238, BC548, ++
2N3826	Si-N	AM/FM-M/O/ZF, 300MHz, B>40	7c	Tix	BF240..241, BF254..255, BF594..595, ++
2N3827	Si-N	=2N3826: B>100	7c	Tix	BF240..241, BF254..255, BF594..595, ++
2N3828	Si-N	TV-ZF, 40V, 0,1A, 0,3W, >360MHz	7c	Sam,Tix	BF198..199, BF224..225, BF596..597, ++
2N3829	Si-P	S, 35V, 0,2A, 0,38W, <25/65ns	2a	Sca,Ssi,Tix	BSS10..11, BSX19..20, 2N2368..69(A), ++
2N383	Ge-P	=2N381: 5MHz	2a(B=case)		ASY77, 2N1189..90
2N3830	Si-N	S, 60V, 1,2A, 1W, <60/70ns	2a	USA,Tix	BSS14, BSV95, 2N3735, 2N5262
2N3831	Si-N	=2N3830: 70V	2a	USA,Tix	BSS14, BSV95, 2N3735, 2N5262
2N3832	Si-N	S, 15V, 0,035A, 0,2W, <35/30ns	5g	Etc,Tix	BSS10..12, BSY17..18, 2N3011, ++
2N3833	Si-N	UHF, 25V, 0,1A, >1GHz	24f	Tix	BFT12, 2SC3288, 2SC3368..69
2N3834	Si-N	UHF, 25V, 0,1A, >1GHz	24f	Tix	BFT12, 2SC3288, 2SC3368..69
2N3835	Si-N	UHF, 25V, 0,1A, >1GHz	24f	Tix	BFT12, 2SC3288, 2SC3368..69
2N3836	Si-N-Darl	NF/S-L, 60V, 7A, 25W, B>1000		Tix	—
2N3837	Si-N-Darl	=2N3836: 100V		Tix	—
2N3838	Si-N/P	NPN+PNP, 60V, 0,6A, 0,35W, >200MHz	10-FLP	Mot,Ray,Tix	—
2N3839	Si-N	UHF-V/M/O, 30V, 0,04A, 0,2W, >1GHz	5g	USA,Mot,Sgs	BF357, BF377..378, 2SC2498, 2SC3037, ++
2N384	Ge-P	RF/IF AMP, 20V, 10mA, 0,08W, 400MHz	4g	Sty	AF106, AF124..125, AF200
2N384/33	Ge-P	=2N384:	5g	Syl	AF106, AF124..125, AF200
2N3840	Si-P	Chopper, 50/50/50V, 0,1A, 0,4W	2a	Sem,Spr,Tdy	2N2946
2N3841	Si-P	Chopper. 100/100/60V, 0,1A, 0,3W	2a	Sem,Sty	—
2N3842	Si-P	Chopper, 120/120/120V, 0,1A, 0,3W	2a	Sem,Sty	—
2N3843(A)	Si-N	HF-V/M/ZF, 30V, 0,1A, 0,2W, >60MHz	7c	USA,Gen,Mic	BF240..241, BF254..255, BF594..595, ++
2N3844(A)	Si-N	HF-V/M/ZF, 30V, 0,1A, 0,2W, >90MHz	7c	USA,Gen,Mic	BF240..241, BF254..255, BF594..595, ++
2N3845(A)	Si-N	HF-V/M/ZF, 30V, 0,1A, 0,2W, >120MHz	7c	USA,Gen,Mic	BF240..241, BF254..255, BF594..595, ++
2N3846	Si-N	S-L, 300/200V, 20A, 150W(Tc=100°)	49m	USA,Tix	2N6324..25
2N3847	Si-N	=2N3846: 400/300V	49m		2N6325
2N3848	Si-N	S-L, 300/200V, 20A, 150W(Tc=100°)	49m	USA,Tix	2N6324..25
2N3849	Si-N	=2N3848: 400/300V	49m		2N6325
2N385	Ge-N	HF/S, 25V, 0,2A, 0,15W, 6MHz	2a	USA	ASY28..29, ASY73..75
2N3850	Si-N	S-L, 100/60V, 5A, 40W(Tc=100°), B>50	49m	USA,Tix	2N5002, 2N5004, 2N5284..85
2N3851	Si-N	=2N3850: B>30	49m		2N5002, 2N5004, 2N5284..85
2N3852	Si-N	=2N3850: 60V	49m		2N5002, 2N5004, 2N5284..85
2N3853	Si-N	=2N3850: 60V, B>30	49m		2N5002, 2N5004, 2N5284..85
2N3854	Si-N	Uni, 18V, 0,1A, 0,2W, >100MHz, B>35	7c	USA,Gen,Mic	BC168, BC183, BC238, BC548, ++
2N3854A	Si-N	=2N3854: 30V	7c		BC168, BC183, BC238, BC548, ++
2N3855	Si-N	=2N3854: >130MHz, B>60	7c		BC168, BC183, BC238, BC548, ++
2N3855A	Si-N	=2N3855: 30V	7c		BC168, BC183, BC238, BC548, ++
2N3856	Si-N	=2N3854: >140MHz, B>100	7c		BC168, BC183, BC238, BC548, ++
2N3856A	Si-N	=2N3856: 30V	7c		BC168, BC183, BC238, BC548, ++
2N3857	Si-P	NF, 45V, 0,5A, 0,6W, >20MHz	2a	Sty	BC160..161, BC303..304, BC638, ++
2N3858	Si-N	Uni, 30V, 0,1A, 0,38W, 125MHz, B>60	7c	USA,Mic,++	BC168, BC183, BC238, BC548, ++
2N3858A	Si-N	=2N3856: 60V	7c		BC174, BC182, BC190, BC546, ++
2N3859	Si-N	=2N3856: 140MHz, B>100	7c		BC168, BC183, BC238, BC548, ++
2N3859A	Si-N	=2N3859: 60V	7c		BC174, BC182, BC190, BC548, ++
2N385A	Ge-N	=2N385: 40V, 8MHz	2a		—
2N386	Ge-P	NF/S-L, 60V, 3A, 12,5W(Tc=75°)	~23	Phc	AL102..103, AUY19..20, 2N2144..46, ++
2N3860	Si-N	=2N3858: 170MHz, B>150	7c		BC168, BC183, BC238, BC548, ++
2N3860A	Si-N	=2N3860: 60V	7c		BC174, BC182, BC190, BC548, ++
2N3861	Si-N	S/Vid, 530/530V, 0,025A, >50MHz	43m	USA	(BD232, BD410, BUX88..87, 2SC2699)
2N3862	Si-N	S, 50V, 0,2A, 0,38W, <78/50ns	5g	USA	BSX39, 2N4014..14, 2SC1834
2N3863	Si-N	S-L, 70V, 7,5A, 117W, >0,5MHz	23a	USA	BD313, BD545B, 2N3055, 2N5632..34, ++
2N3864	Si-N	=2N3863: 110V	23a		BD313, BD545D, 2N3055, 2N5632..34, ++
2N3865	Si-N	=2N3863: 160V	23a		BDX11, BDY54, 2N3442, 2SD733, ++
2N3866(A)	Si-N	VHF/UHF-O/Tr, 55V, 0,4A, PQ>1W(400MHz)	2a	USA,EUR	BFR97
2N3867	Si-P	NF/S, 40V, 3A, 1W, >60MHz, <100/400ns	2a	USA,Mot,Sgs	2N3719..20

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2N3868	Si-P	=2N3887: 60V	2a		2N3720
2N3869	Si-N	HF-Tr, 40V, 0,5A, >400MHz	2a	USA,Nec	BFS51, BFR98, BLW16, 2SC2852, ++
2N387	Ge-P	NF/S-L, 60V, 3A, 12,5W(Tc=75°)	=23	Phc	AL102..103, AUY20, 2N2141, 2N2146, ++
2N3870	50Hz-Thy	100V, 22A(Tc=85°), Igt/Ih<40/<70mA	29b	Gen,Mot,Rca	MCR3835-3, BStE4026M, MCR63-3
2N3871	50Hz-Thy	=2N3870: 200V	29b		MCR3835-4, BStE4026M, MCR63-4
2N3872	50Hz-Thy	=2N3870: 400V	29b		MCR3835-6, BStE4026M, MCR63-6
2N3873	50Hz-Thy	=2N3870: 600V	29b		MCR3835-8, BStE4040M, MCR63-8
2N3876	Si-N	NF/S-L, 140V, 10A, 125W, >50MHz		Ssi,Trw	—
2N3877	Si-N	Nix, 70V, 0,05A, 0,2W, 160MHz	7c	USA,Mic,Nsc	BC546, BSS38, BSX21, 2SC1890(A), ++
2N3877A	Si-N	=2N3877: 85V	7c		BC546, BSS38, BSX21, 2SC1890(A), ++
2N3878	Si-N	NF/S-L, 120V, 4A, 35W, >40MHz	22a	USA,Rca,Tix	BDV10..12, BDY79, 2SD722(A, B)
2N3879	Si-N	NF/S-L, 120V, 7A, 35W, >40MHz	22a	USA,Rca,Tix	MJE15030
2N388	Ge-N	S, 25V, 0,2A, 0,15W, 17MHz	2a(B=case)	USA,Tix	ASY28..29, ASY73..75
2N3880	Si-N	UHF, 30V, 0,2W, >1200MHz	5g	USA,Fch,Sgs	BF357, BF377..376, BFR37, BFW99, ++
2N3881	Si-N	NF, 60V, 1A, 0,6W, >70MHz	2a	Idi,Sca,Ssi	BC140..141, 2N1990, 2N2102, 2N2405, ++
2N3882	MOS-P-FET-e	Uni, 30V, Idss>0,25mA, Up<3V	5k(DGSsub)	Ray	—
2N3883	Ge-P	S, 25V, 0,3A, 0,3W, 300MHz, 36/68ns	2a	Mot,Ssi	—
2N388A	Ge-N	=2N388: 40V	2a(B=case)		—
2N389(A,/I)	Si-N	NF/S-L, 60V, 3A, 85W		USA,Tix	2N1722..23, (BD241A, BD535, BD935, ++)
2N3898	50Hz-Thy	100V, 22A(Tc=85°), Igt/Ih<40/<70mA	21b	USA,Mot,Rcc	MCR70-3, C228A, MCR3935-3, BStE4126M, ++
2N3897	50Hz-Thy	=2N3898: 200V	21b		C228B, MCR3935-4, BStE4128M, C35B, ++
2N3898	50Hz-Thy	=2N3898: 400V	21b		C228D, MCR3935-6, BStE4126M, C35D, ++
2N3899	50Hz-Thy	=2N3898: 800V	21b		C228M, MCR3935-8, BStE4140M, C35M, ++
2N39	Ge-P	NF/HF, 30V, 300mA, 0,05W	2a	Cbs	(AC125..128, AC151, ASY26..27)
2N3900(A)	Si-N	Uni, ra, 18V, 0,1A, 0,36W, 160MHz	7c	USA,Mic,Nsc	BC169, BC184, BC239, BC549, ++
2N3901	Si-N	Uni, 18V, 0,1A, 0,38W, 200MHz	7c	USA,Mic,Nsc	BC188, BC183, BC238, BC548, ++
2N3902	Si-N	S-L, 700/325V, 2,5A, 100W(Tc=75°)	23a	USA,Mot,Tix	BUS11(A), BUX46(A), 2SC3091, 2SC3155
2N3903	Si-N	Uni, 60V, 0,2A, 0,625W, >250MHz, B>50	7e	USA,EUR	BC174, BC162, BC190, BC546, ++
2N3904	Si-N	=2N3903: B>100	7e		BC174, BC162, BC190, BC548, ++
2N3905	Si-P	Uni, 40V, 0,2A, 0,625W, >200MHz, B>50	7e	USA,EUR	BC212, BC257, BC307, BC557, ++
2N3906	Si-P	=2N3905: B>100	7e		BC212, BC257, BC307, BC557, ++
2N3907	Si-N	Dual, 60V, 0,03A, 0,6W, >60MHz, B>60	TO-77	USA,Mic,Nsc	BFY81, 2N2919..20
2N3908	Si-N	=2N3907: B>100	TO-77		BFY81, 2N2919..20
2N3909(A)	P-FET	Uni, 20V, Idss>0,3mA, Up<8V	5n	USA,Mot,Tix	BF320, 2N3820, 2N5800
2N391	Ge-P	NF/S-L, 50V, 5A		Del	—
2N3910	Si-P	Chopper, 60/50/50V, 0,2A, 0,5W	2a	USA	—
2N3911	Si-P	Chopper, 60/40/40V, 0,2A, 0,5W	2a	USA	—
2N3912	Si-P	Chopper, 60/30/30V, 0,2A, 0,5W	2a	USA	—
2N3913	Si-P	=2N3910: 0,4W	2a		—
2N3914	Si-P	=2N3911: 0,4W	2a		—
2N3815	Si-P	=2N3912: 0,4W	2a		—
2N3816	Si-N	S/Vid, 150/150V, 0,15A, 5W, >50MHz	43m	USA	(BF380, BF415, MJE340, 2SC2376, ++)
2N3917	Si-N	S-L, 60V, 2A, 20W(Tc=46°), >60MHz, B>30	23a	USA,Tix	2SC1195
2N3918	Si-N	=2N3917: B>100	23a		2SC1195
2N3919	Si-N	S-L, 120V, 10A, 15W(Tc=75°), >60MHz, B>40	23a	USA,Tix	BUW70, BUY55, 2SC2769
2N392	Ge-P	NF-L, 80V, 5A	23a	USA	2N1535..38, 2N1545..48, 2N3615..18, ++
2N3920	Si-N	=2N3919: B>100	23a		BUW70, BUY55, 2SC2769
2N3921	N-FET	Dual, ra, 50V, Idss>1mA, Up<3V	TO-71	USA,Isi,Nsc	BFQ10..18, 2N3954..59
2N3922	N-FET	Dual, ra, 50V, Idss>1mA, Up<3V	TO-71	USA,Isi,Nsc	BFQ10..16, 2N3954..59
2N3923	Si-N	Vid, 150V, 0,05A, 0,8W, >40MHz	2a	USA,Fch	BF257..259, BF657..859, 2N5058..59, ++
2N3924	Si-N	VHF-Tr/E, 38V, 0,5A, PQ=4W(175MHz)	2a	Mot,Phi,Sem	BFS22, BFW46, BLY33, MRF237
2N3924	Si-N			Tho,Tix,Val	—
2N3925	Si-N	VHF-Tr/E, 36V, 1A, PQ=5W(175MHz)	49m	Mot	BLY55, BLY57, BLY78
2N3928	Si-N	VHF-L, 36V, 1,5A, PQ=7W(175MHz)	49a	=2N3924	BLW35, BLY58
2N3927	Si-N	VHF-L, 36V, 3A, PQ=12W(175MHz)	49a	=2N3924	BLY58
2N3928	Si-N	S, 60V, 3A, 5W(Tc=25°), <35/75ns	2a	Idi,Sol,Tix	2N3507
2N3929	Si-N	=2N3928: 20W	49m		—
2N393	Ge-P	HF/S, Chopper, 6/6/6V, 0,05A, 50MHz	37d	Csr,Spr	—
2N3930	Si-P	Vid, 180V, 0,05A, 0,4W, >40MHz	2a	Fch,Sca,Sgs	BF436..437, BF491..493, 2SA1370..71, ++
2N3931	Si-P	=2N3930: 0,7W	2a		BFQ36..37, BFT44..45, 2SB606, ++
2N3932	Si-N	VHF/UHF, 30V, 0,2W, >750MHz	5g	USA,Mic,Rcc	BF377..378, BF689, BF783, 2N2857, ++
2N3933	Si-N	VHF/UHF, 40V, 0,2W, >750MHz	5g	USA,Mic,Rcc	BF377..378, BF689, BF783, 2N2857, ++
2N3934	N-FET	Dual, ra, 50V, Idss>0,3mA, Up<3V	TO-71	Nsc,Tsc	BFQ10..18, 2N3954..59
2N3935	N-FET	Dual, ra, 50V, Idss>0,3mA, Up<3V	TO-71	Nsc,Tsc	BFQ10..16, 2N3954..59
2N3938	50Hz-Thy	100V, 7A(Tc=80°), Igt/Ih<60/<110mA	21b	Ssi,Tag,Tix	BTW42/600R, TAG9N400, TAG15-100, ++
2N3937	50Hz-Thy	=2N3936: 200V	21b		BTW42/600R, TAG9N400, TAG15-200, ++

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2N3938	50Hz-Thy	=2N3938: 300V	21b		BTW42/600R, TAG9N400, TAG15-300, ++
2N3939	50Hz-Thy	=2N3938: 400V	21b		BTW42/600R, TAG9N400, TAG15-400, ++
2N394	Ge-P	HF/S, 10/10/10V, 0,2A, 0,15W	2a(B=case)	USA	(ASY26..27, ASY48, ASY78..77)
2N3940	50Hz-Thy	=2N3938: 500V	21b		BTW42/600R, TAG9N600, TAG15-600, ++
2N3941	Si-N	Dual, 60V, 0,05A, 0,75W, >200MHz	TO-77	Sol,Sty	2N3409..11
2N3942	Si-N	Dual, 80V, 0,05A, 0,75W, >200MHz	TO-77		2N3409..11
2N3943	Si-N	Dual, 60V, 0,05A, 0,75W, >200MHz	TO-71		—
2N3944	Si-N	Dual, 60V, 0,05A, 0,75W, >200MHz	TO-71		—
2N3945	Si-N	Uni, 70V, 1A, 5W(Tc=25°), >60MHz	2a	USA,Mic,Nsc	BC140..141, 2N1890, 2N2102, 2N2405, ++
2N3946	Si-N	NF/S, 60V, 0,2A, 0,36W, <70/375ns, B>50	2a	USA,Mic,Mot	BC182, BC546, 2N2221..22(A), ++
2N3947	Si-N	=2N3946: B>100	2a		BC182, BC548, 2N2221..22(A), ++
2N3948	Si-N	UHF-A/O/Tr, 38V, 0,4A, PQ>1W(400MHz)	2a	USA,Mot,Tix	BFS50, MRF629, 2SC2762, 2SC3185
2N394A	Ge-P	=2N394: 30/15/20V	2a(B=case)		(ASY26, ASY48, ASY76..77)
2N395	Ge-P	S, 30V, 0,2A, 0,15W, 5MHz	2a(B=case)	USA,Tix	ASY26, ASY48, ASY76..77
2N3950	Si-N	AM/FM-L, 85V, 3,3A, PQ=50W(50MHz)	49a	USA, Mot	—
2N3953	Si-N	UHF, 15V, 0,03A, 0,2W, >1300MHz	5g	Sca,Ssi	BF377..378, BF698, BF763, 2N2857, ++
2N3954(A)	N-FET	Dual, VHF, ra, 50V, Idss>0,5mA, Up<4,5V	TO-71	USA,Nsc,Tix	BFQ10..18, 2N3921..22
2N3955(A)	N-FET	Dual, VHF, ra, 50V, Idss>0,5mA, Up<4,5V	TO-71	USA,Nsc,Tix	BFQ10..16, 2N3921..22
2N3956	N-FET	Dual, VHF, ra, 50V, Idss>0,5mA, Up<4,5V	TO-71	USA,Nsc,Tix	BFQ10..16, 2N3921..22
2N3957	N-FET	Dual, VHF, ra, 50V, Idss>0,5mA, Up<4,5V	TO-71	USA,Nsc,Tix	BFQ10..18, 2N3921..22
2N3958	N-FET	Dual, VHF, ra, 50V, Idss>0,5mA, Up<4,5V	TO-71	USA,Nsc,Tix	BFQ10..16, 2N3921..22
2N3959	Si-N	SS, 20V, 0,03A, 0,4W, 5,4/4,9ns	2a	USA, Mot	—
2N396(A)	Ge-P	S, 30V, 0,2A, 0,15..0,2W, 9MHz	2a(B=case)	USA,Tix	ASY26, ASY48, ASY76..77
2N3960	Si-N	SS, 20V, 0,03A, 0,4W, 5,4/4,9ns	2a	USA, Mot	—
2N3981	Si-N	VHF-Tr/E, 65V, 1A, PQ=4W(175MHz)	49m	USA, Mot	BLY60
2N3962	Si-P	NF, ra, 60V, 0,2A, 0,36W, >40MHz	2a	USA,EUR	2SA970, 2SA1049, 2SA1138..37
2N3963	Si-P	NF, ra, 80V, 0,2A, 0,38W, >40MHz	2a	USA,EUR	2SA970, 2SA1049, 2SA1138..37
2N3984	Si-P	NF, ra, 45V, 0,2A, 0,36W, >50MHz	2a	USA,EUR	BC418, BC560, 2SA970, 2SA1138..37, ++
2N3985	Si-P	NF, ra, 60V, 0,2A, 0,36W, >50MHz	2a	USA,EUR	2SA970, 2SA1049, 2SA1138..37
2N3966	N-FET	S, 30V, Idss>2mA, Up<6V, <120/100ns	5k	USA,EUR,Mic	BFS76, BFS79
2N3967(A)	N-FET	Uni, 30V, Idss>2,5mA, Up<8V	5k	USA,Nsc	BF256A, BFS71, 2N3822, 2N4221, ++
2N3968(A)	N-FET	Uni, 30V, Idss>1mA, Up<3V	5k	USA,Nsc	BFW12, 2N4340, 2N5484
2N3969(A)	N-FET	Uni, 30V, Idss>0,4mA, Up<1,7V	5k	USA,Nsc	2N4339, 2N5356, 2SK83, 2SK195, 2SK238
2N397	Ge-P	S, 30V, 0,2A, 0,15W, 13MHz	2a(B=case)	USA,Tix	ASY26, ASY48, ASY78..77
2N3970	N-FET	S, Chopper, 40V, Idss>50mA, Up<10V	2b	USA,Mot,Tix	BFS74, BFS77..78, 2N4391, 2N4856
2N3971	N-FET	S, Chopper, 40V, Idss>25mA, Up<5V	2b	USA,Mot,Tix	2N4392, 2N5434
2N3972	N-FET	S, Chopper, 40V, Idss>5mA, Up<3V	2b	USA,Mot,Tix	2N4393
2N3973	Si-N	NF/S, 60V, 0,4A, 0,38W, <60/110ns	7c	Gen,Sam,Spr	BSV59, BSX49, 2N2221..22(A), 2N4014, ++
2N3974	Si-N	NF/S, 60V, 0,4A, 0,38W, <80/110ns	7c	Gen,Sem,Spr	BSV59, BSX49, 2N2221..22(A), 2N4014, ++
2N3975	Si-N	NF/S, 60V, 0,4A, 0,38W, <60/200ns	7c	Gen,Sem,Spr	BSV59, BSX49, 2N2221..22(A), 2N4014, ++
2N3976	Si-N	NF/S, 60V, 0,4A, 0,38W, <60/200ns	7c	Gen,Sem,Spr	BSV59, BSX49, 2N2221..22(A), 2N4014, ++
2N3977	Si-P	Chopper, 15/10/15V, 0,1A, 0,4W	2a	Spr,Ssi	2N2944
2N3978	Si-P	Chopper, 25/20/25V, 0,1A, 0,4W	2a	USA, Mot	2N2945
2N3979	Si-P	Chopper, 40/35/40V, 0,1A, 0.4W	2a	Spr,Ssi,Tdy	2N2946
2N398+A13418	Ge-P	NF/S, 105V, 0,1A, 0,05W	2a	USA,Mot,Tix	ACY39, 2N2042..43
2N3960	UJT-P	Ip<2μA, Iv>1mA	5a	Mot,Tix	—
2N3981	Si-N	S, 60V, 1A, 0,8W, <35/40ns	2a	Nsc,Sty	BSS27, BSV77, BSV95, 2N5189, +++
2N3962	Si-N	=2N3981: 50V	2a	Nsc,Sty	BSS27, BSV77, BSV95, 2N5189, +++
2N3983	Si-N	VHF, 30V, 0,03A, 0,2W, >500MHz	7c	Sem,Sty	BF225, BF310, BF314, BF502, BF505++
2N3984	Si-N	VHF, 30V, 0,03A, 0,2W, >400MHz	7c	Sem,Sty	BF225, BF310, BF314, BF502, BF505++
2N3985	Si-N	VHF, 30V, 0,03A, 0,2W, >300MHz	7c	Sem,Sty	BF225, BF310, BF314, BF502, BF505++
2N398A	Ge-P	=2N398: 0,2A, 0,15W	2a		ACY39, 2N2042..43
2N398B	Ge-P	=2N398: 0,25W	2a		ACY39, 2N2042..43
2N399	Ge-P	NF-L, -/40V, 3A, 45W(Tc=45°)	23a	USA	AD149, AUY19..20, 2N2143..46, ++
2N3993(A)	P-FET	S, Chopper, 25V, Idss>10mA, Up<9,5V	5n	USA,Mot,Tix	*MPF970
2N3994(A)	P-FET	S, Chopper, 25V, Idss>2mA, Up<5,5V	5n	USA,Mot,Tix	MPF971
2N3995	Ge-P	VHF, 20V, 0,1A, 0,3W, >600MHz	2a	Tix	2N2929
2N3998	Si-N	S-L, 100V, 5A, 30W(Tc=100°), >40MHz	50g	USA,Tix	2N5002, 2N5004, 2N5284..85
2N3997	Si-N	S-L, 100V, 5A, 30W(Tc=100°), >40MHz	50g	USA,Tix	2N5002, 2N5004, 2N5284..85
2N3998	Si-N	S-L, 100V, 5A, 30W(Tc=100°), >40MHz	=49m	USA,Tix	2N5002, 2N5004, 2N5284..85
2N3999	Si-N	S-L, 100V, 5A, 30W(Tc=100°), >40MHz	=49m	USA,Tix	2N5002, 2N5004, 2N5284..85
2N40	Ge-P	NF/HF, 30V, 300mA, 0,05W	2a	Cbs	(AC125..126, AC151, ASY26..27)
2N400	Ge-P	NF-L, 50/40V, 3A, 45W(Tc=45°)	23a	USA	AD149, AUY19..20, 2N2143..48, ++
2N4000	Si-N	S, 100V, 1A, 15W(Tc=100°), >40MHz	2a	USA,Tix	BUX49, BUY41
2N4001	Si-N	=2N4000: 120V	2a		BUX49, BUY41
2N4002	Si-N	S-L, 100V, 30A, 100W(Tc=100°), >30MHz	49m	USA,Tix	2N282425

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2N4003	Si-N	=2N4002: 120V	49m		2N2825
2N4004	Si-N	S-L, 100V, 20A, 40W(Tc=100°), >30MHz		USA,Tix	2N3263..64
2N4005	Si-N	=2N4004: 120V			2N3263..64
2N4006	Si-P	Chopper, 10/6/10V, 0,1A, 0,4W	2a	Spr,Ssi,Tdy	2N2944
2N4007	Si-P	Chopper, 20/15/20V, 0,1A, 0,4W	2a	Spr,Ssi,Tdy	2N2945
2N4008	Si-P	Chopper, 35/30/35V, 0,1A, 0,4W	2a	Spr,Ssi,Tdy	2N2946
2N4009	Si-P	=2N4006: gep	2a		2N2944
2N401	Ge-P	NF-L, -/40V, 3A, 45W(Tc=45°)	23a	USA	AD149, AUY19..20, 2N2143..46,++
2N4010	Si-P	=2N4007: gep	2a		2N2945
2N4011	Si-P	=2N4006: gep	2a		2N2946
2N4012	Si-N	VHF/UHF-L, 65V, 1,5A, PQ=3W(800MHz)	49a	USA,Mot,Rca	—
2N4013	Si-N	S, 50V, 1A, 0,36W, 20/55ns	2a	USA,Mot,Tix	2N3736..37
2N4014	Si-N	=2N4013: 80V, 20/50ns	2a		2N3737
2N4015	Si-P	Dual, ra, 80V, 0,3A, 0,5W, >200MHz	TO-77	Fch,Mic,Mot	—
2N4015	Si-P			Nsc,Sca,Sgs	—
2N4016	Si-P	Dual, ra, 80V, 0,3A, 0,5W, >200MHz	TO-77		—
2N4017	Si-P	Dual, ra, 80V, 0,2A, 0,6W, >40MHz	TO-77	Fch,Mic,Nsc	—
2N4017	Si-P			Sca,Sgs,Ssi	—
2N4018	Si-P	Dual, ra, 80V, 0,2A, 0,6W, >40MHz	TO-77		2N4015..16
2N4019	Si-P	Dual, ra, 45V, 0,2A, 0,6W, >40MHz	TO-77		2N4015..16
2N402	Ge-P	NF, 25V, 0,15A, 0,18W, B=25	2a	USA	AC125..126, AC151, 2SB54, 2SB56
2N4020	Si-P	Dual, ra, 45V, 0,2A, 0,6W, >40MHz	TO-77		2N4015..16
2N4021	Si-P	Dual, ra, 80V, 0,2A, 0,6W, >40MHz	TO-77		2N4015..18
2N4022	Si-P	Dual, ra, 80V, 0,2A, 0,6W, >40MHz	TO-77		2N4015..16
2N4023	Si-P	Dual, ra, 45V, 0,2A, 0,6W, >40MHz	TO-77		2N4015..16
2N4024	Si-P	Dual, ra, 80V, 0,2A, 0,6W, >40MHz	TO-77		2N4015..16
2N4025	Si-P	Duel, ra, 80V, 0,2A, 0,8W, >40MHz	TO-77		2N4015..16
2N4026	Si-P	S, 80V, 1A, 0,5W, <100/400ns, B>40	2a	USA,Mic,Mot	BC327A, BC636, BC640, 2N2908..07(A)++
2N4026	Si-P			Phi,Sgs,Tix	—
2N4027	Si-P	=2N4026: 80V	2a		BC640, BCX39, 2SB647, 2N2906..07A,++
2N4028	Si-P	=2N4026: B>100	2a		BC327A, BC636, BC640, 2N2908..07(A)++
2N4029	Si-P	=2N4026: 80V, B>100	2a		BC640, BCX39, 2SB647, 2N2906..07A,++
2N403	Ge-P	=2N402 B=33	2a	USA	AC125..126, AC151, 2SB54, 2SB56
2N4030	Si-P	=2N4026: 0,8W	2a		BC161, BCX60, BSW40, 2N2904..05(A),++
2N4031	Si-P	=2N4027: 0,8W	2a		BCX80, BSW40, 2N2904..05A, 2N4036
2N4032	Si-P	=2N4028: 0,8W	2a		BC161, BCX60, BSW40, 2N2904..05(A),++
2N4033	Si-P	=2N4029.C135340,8W	2a		BCX80, BSW40, 2N290405A, 2N4036
2N4034	Si-P	HF/S, 40V, 0,1A, 0,36W, <40/150ns, B>70	2a	USA,Sgs	BFX48, BSW24, BSX36, 2N3250..51(A)
2N4035	Si-P	=2N4034: B>150	2a		BFX48, BSW24, BSX36, 2N3250..51(A)
2N4036	Si-P	NF/S, 90V, 1A, 1W, <110/700ns	2a	USA,EUR	BCX80, BFR23, BSW40
2N4037	Si-P	NF/S, 60V, 1A, 1W, >60MHz	2e	USA,EUR	BC161, BCX60, BFR24, BSW40,++
2N4036	MOS-N-FET-d	Uni, 50V, Idss<0,1mA, Up<2V	5n	Gle,Trw	—
2N4039	MOS-N-FET-d	Uni, 50V, Idss>0,1mA, Up<6V	5n	Gle,Trw	—
2N404	Ge-P	S, 25V, 0,15A, 0,15W	2a	USA,Mot,Tix	ASY26..27, ASY48, ASY76..77
2N4040	Si-N	UHF-L, 65V, 3A, PQ>8W(400MHz)	55r	USA,Fer,Tix	BLW94, BLX94..95, MRF323, 2SC1116
2N4041	Si-N	UHF-L, 85V, 1A, PQ>3,3W(400MHz)	55r	USA,Fer,Tix	BLW93, BLX93, MRF321, 2SC1040
2N4042	Si-N	Dual, ra, 80V, 0,01A, 0,5W, >200MHz	TO-70	Sol,Sty	—
2N4043	Si-N	Dual, ra, 45V, 0,01A, 0,5W, >150MHz	TO-70		—
2N4044	Si-N	=2N4042: 0,75W	TO-77		—
2N4045	Si-N	=2N4043: 0,75W	TO-77		—
2N4046	Si-N	S, 50V, 0,5A, 0,8W, <45/75ns	2a	USA,Sgs,Nsc	BSS27..29, BSV77, 2N3724, 2SC1365,++
2N4047	Si-N	=2N4046: 80V, 45/100ns	2a		BSV95, 2N3722..23, 2N3725, 2SC1069,++
2N4048	Ge-P	S-L, 45V, 80A, 170W, B>80	38a	Gpd,Mot,Stc	MP500, MP504
2N4049	Ge-P	=2N4048: 60V	38a		MP501, MP505
2N404A	Ge-P	=2N404: 40V	2a		—
2N405	Ge-P	NF, 20V, 35mA, 0,15W	1a	USA	AC125..126, AC151, 2SB54, 2SB56
2N4050	Ge-P	=2N4048: 75V	38a		MP502, MP506
2N4051	Ge-P	=2N4048: B>120	38a		MP500, MP504
2N4052	Ge-P	=2N4048: 80V, B>120	38a		MP501, MP505
2N4053	Ge-P	=2N4048: 75V, B>120	38a		MP502, MP506
2N4054	Si-N	Vid, 300V, 0,1A, 4W(Tc=75°), >15MHz	13h	Gen,Sty	BF617, BF756..759, BF859
2N4055	Si-N	=2N4054: 250V	13h		BF615, BF617, BF757..759, BF858..859
2N4056	Si-N	=2N4054: 200V	13h		BF615, BF617, BF757..759, BF858..859
2N4057	Si-N	=2N4054: 150V	13h		BF615, BF617, BF757..759, BF858..859
2N4059	Si-P	NF-V, ra, 30V, 0,03A, 0,36W	7c	USA,Tix,++	BC214, BC259, BC309, BC559,++
2N4059	Si-P	NF, 30V, 0,03A, 0,36W, B>45	7c	USA,Tix,++	BC213, BC256, BC306, BC556,++

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2N406	Ge-P	=2N405:	2a	USA	AC125..126, AC151, 2SB54, 2SB56
2N4061	Si-P	=2N4060: B>90	7c		BC213, BC258, BC308, BC558,++
2N4062	Si-P	=2N4060: B>180	7c		BC213, BC258, BC308, BC558,++
2N4063	Si-N	=2N3439: 10W	43m	USA,Rca	(BD410, 2SC3051, 2SC3425)
2N4064	Si-N	=2N3440: 10W	43m	USA,Rca	(BD410, BF468, BF668, 2SC3051,++)
2N4065	MOS-P-FET-e	HF/S, 30V, Idss<12mA, Up<6V	5(DGsubS)	Fch,Gie	—
2N4066	MOS-P-FET-e	Dual, Chopper, 30V, 0,2A, Up<6V	TO-77	Gie,Mot	—
2N4067	MOS-P-FET-e	Dual, Chopper, 30V, 0,2A, Up<6V	TO-77	Gie,Mot	—
2N4066	Si-N	Vid, 150V, 0,2A, 0,5W, >50MHz	2a	Spe,Ssi	BF257..259, BF657..659, 2N5058..59,++
2N4069	Si-N	=2N4068: 1W	2a°		BF257..259, BF657..659, 2N5058..59,++
2N407	Ge-P	HF, 20V, 70mA, 0,15W, 6,8MHz	1A	USA	ASY26..27
2N4070	Si-N	S-L, 120/100V, 10A, 115W, >20MHz	23a	USA	BUW70, BUY55..56, BUX17
2N4071	Si-N	=2N4070: 200V	23a		BUW70, BUY55..56, BUX17
2N4072	Si-N	VHF-Tr, 40V, 0,1A, PQ>0,25W(175MHz)	2a	USA,Mot	BFX59, 2SC2053
2N4073	Si-N	VHF-Tr, 40V, 0,15A, PQ>0,5W(175MHz)	2a	USA,Mot	BFR36, BFW16, MRF207, MRF607
2N4074	Si-N	Uni, 40V, 0,3A, 0,4W, >50MHz	2a	USA	BC337, BC635, BC637, BC639,++
2N4075	Si-N	S-L, 100V, 2A, 30W, >30MHz, B>30	49a	USA,Fch,Phi	2N5002, 2N5004, 2N5284..85
2N4076	Si-N	=2N4076: B>50	49a		2N5002, 2N5004, 2N5264..85
2N4077	Ge-N	NF-L, 32V, 1A, 7,5W(Tc=50°)	23a	Amp,Phi,Spe	(AD161)
2N4078	Ge-P	NF-L, 32V, 1A, 7,5W(Tc=50°)	23a	Amp,Phi,Spe	(AD162)
2N4079	Ge-N/P	=2N4077+4078 gep	23a	Amp,Phi,Spe	(AD161+162)
2N406	Ge-P	=2N407:	2a	USA	ASY26..27
2N4080	Si-P	UHF, 20V, 0,05A, 0,3W, >1GHz	5g	Idi,Sca,Sem	BF316, BF439, BF516, BF606,++
2N4081	Si-N	VHF, ra, 40V, 0,2W, >600MHz	5k	Rca	BF314, BF502, BF505, BF507, BF562++
2N4082	N-FET	Dual, ra, 50V, Idss>0,3mA, Up<3V	TO-71	Isi,Sol,Nsc	BFQ10..16, 2N3954..58
2N4083	N-FET	Dual, ra, 50V, Idss>0,3mA, Up<3V	TO-71	Isi,Sol,Nsc	BFQ10..16, 2N3954..58
2N4084	N-FET	Dual, ra, 50V, Idss>0,3mA, Up<3V	TO-71	Isi,Sol,Nsc	BFQ10..16, 2N3954..58
2N4085	N-FET	Dual, ra, 50V, Idss>0,3mA, Up<3V	TO-71	Isi,Sol,Nsc	BFQ10..16, 2N3954..58
2N4086	Si-N	Uni, 12V, 0,1A, 0,2W, B>150	7c	Gen,Sty	BC168, BC183, BC238, BC548,++
2N4087(A)	Si-N	=2N4086: B>250	7c		BC166, BC183, BC238, BC548,++
2N4088	P-FET	Uni, 30V, Idss>5mA, Up<8V	5k	Tsc	BF320B, 2N5462, 2N5465
2N4089	P-FET	Uni, 30V, Idss>2mA, Up<5V	5k	Tsc	2SJ104, 2SJ107, 2SJ106
2N409	Ge-P	HF, 13V, 15mA, 0,08W, 6,8MHz	1a	USA	AF124..127, AF200
2N4090	P-FET	Uni, 30V, Idss>0,4mA, Up<3V	5k	Tsc	2N2844
2N4091(A)	N-FET	S, Chopper, 40..50V, Idss>30mA, Up<10V	2b	USA,EUR	BFS74, BFS77, 2N4856, 2N4859, 2N4391
2N4092(A)	N-FET	S, Chopper, 40..50V, Idss>15mA, Up<7V	2b	USA,EUR	BFS75, BFS77, 2N4857, 2N4880, 2N4392
2N4093(A)	N-FET	S, Chopper, 40..50V, Idss>8mA, Up<5V	2b	USA,EUR	BFS75, BFS77, 2N4657, 2N4880, 2N4392
2N4094	N-FET	S, 40V, Idss>75mA, 25/40ns	2b	Tsc	2N5433
2N4095	N-FET	S, 40V, Idss>20mA, 35/60ns	2b	Tsc	BFS75, BFS78, BSV79, 2N4857, 2N4860
2N4096	50Hz-Thy	50V, 0,4A(Tc=85°), Igt/Ih<0,2/<2mA	2a	Fch,Sem,Uni	BRY58/60, (2N2323, 2N6333, TAG615-100)
2N4097	50Hz-Thy	=2N4096: 100V	2a		BRY58/100, (2N2324, 2N6334, TAG615-100)
2N4096	50Hz-Thy	=2N4096: 200V	2a		BRY58/200, (2N2326, 2N6335, TAG615-200)
2N4099	Si-N	Dual, ra, 55V, 0.01A, 0,5W, >150MHz	TO-70	Sol,Sty	—
2N41	Ge-P	NF/HF, 25V, 15mA, 0,05W		Rca	(AC125..126, AC151, ASY26..27)
2N410	Ge-P	=2N409:	2a	USA	AF124..127, AF200
2N4100	Si-N	=2N4099: 0,75W	TO-77		—
2N4101	50Hz-Thy	=2N3228: 600V	22a	Rca,Sgs,Tag	BStC0540L, TAG671-600, TAG676-600
2N4102	50Hz-Thy	600V, 1,3A, (Tc=75°), Igt/Ih<15/<20mA	2a	Rca	TAG612-600, TAG613-600, TAG606-600,++
2N4103	50Hz-Thy	=2N3668: 600V	23a	Rca	2N2579
2N4104	Si-N	Uni, ra, 80V, 0,05A, 0,3W, >60MHz	2a	Idi,Sca,Tix	2N2483..84, 2N3117, 2SC2240, 2SC2459,++
2N4105	Ge-N	NF, 25V, 1A	2a	USA, Phi	AC176, AC187
2N4106	Ge-P	NF, 25V, 1A	2a	USA, Phi	AC128, AC153, AC166
2N4107	Ge-N/P	NF, 25V, 1A	2a	USA, Phi	AC153+176, AC187+166
2N4106	50Hz-Thy	=2N4096:	2a	USA,Fch,Tag	→2N4096
2N4109	50Hz-Thy	=2N4096:	2a	USA,Fch,Tag	→2N4096
2N411	Ge-P	HF, 13V, 15mA, 0,08W, 16MHz	1A	USA	AF124..127, AF200
2N4110	50Hz-Thy	=2N4096:	2a	USA,Fch,Tag	→2N4096
2N4111	Si-N	S-L, 100V, 5A, 30W(Tc=50°), >50MHz, B>40	23a	USA	BDY90..91
2N4112	Si-N	=2N4111: B>100	23a		BDY90..91
2N4113	Si-N	=2N4111: 120V	23a		BDY90
2N4114	Si-N	=2N4111: 120V, B>100	23a		BDY90
2N4115	Si-N	S-L, 120V, 5A, 37W(Tc=100°), >50MHz	49a	USA	2N5284..65
2N4116	Si-N	S-L, 120V, 5A, 37W(Tc=100°), >70MHz	49m	USA	2N5264..65
2N4117(A)	N-FET	Uni, 40V, Idss>0,02mA, Up<1,8V	5k	USA,Mot,Tho	2SK92..93, 2SK103
2N4118(A)	N-FET	Uni, 40V, Idss>0,08mA, Up<3V	5k	USA,Mot,Tho	2N3367, 2N3370
2N4119(A)	N-FET	Uni, 40V, Idss>0,2mA, Up<6V	5k	USA,Mot,Tho	2N3366

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2N412	Ge-P	=2N411	2a	USA	AF124..127, AF200
2N4120	MOS-P-FET-e	S, 30V, Idss>0,5nA, Up<6V	5(DGsubS)	Fch,Gie	—
2N4121	Si-P	Uni, 40V, 0,1A, 0,2W, <45/180ns, B>70	8a	USA,Mic,Sgs	BFX48, BSW24, BSX36, 2N3905..06,++
2N4122	Si-P	=2N4122: B>150	8a		—
2N4123	Si-N	NF/S, 40V, 0,2A, 0,625W, 37/136ns	7e	USA,Fer,Mot	BC237, BC547, BSW41, 2N2221..22(A),++
2N4123	Si-N			Phi,Tix,++	—
2N4124	Si-N	NF/S, 30V, 0,2A, 0,625W, 37/136ns	7e		BC236, BC548, BSW41, 2N2221..22(A),++
2N4125	Si-P	NF/S, 30V, 0,2A, 0,625W, 43/155ns	7e	USA,Fer,Mot	BC308, BC556, BSW24, 2N2906..07(A),++
2N4125	Si-P			Phi,Tix,++	—
2N4126	Si-P	NF/S, 25V, 0,2A, 0,625W, 43/155ns	7e		BC308, BC558, BSW24, 2N2906..07(A),++
2N4127	Si-N	VHF-L, 60V, 2APQ>13,5W(175MHz)	55r	USA,Fer,Tix	BLW24, BLY92..93, 2SC2887
2N4128	Si-N	VHF-L, 60V, 4A PQ>24W(175MHz)	55r	USA,Fer,Tix	MRF314A, 2SC2888
2N413(A)	Ge-P	NF/HF, 30V, 0,4A, 0,2W	2a	USA	ASY76..77
2N4130	Si-N	AM/FM-L, 80V, 10A, PQ=50W(70MHz)	23a	USA, Mot	—
2N4131	Si-N	HF-L, 90V, 5A, 60W, >150MHz	23a	Ker,Sca,Ssi	—
2N4132	Si-N	HF-L, 90V, 0,6A, 7,5W, >200MHz	43a	Ker,Sca,Ssi	—
2N4133	Si-N	HF, 90V, 0,6A, >200MHz	2a	Ker,Sce,Ssi	—
2N4134	Si-N	VHF/UHF/ZF, 30V, 0,03A, 0,2W, >350MHz	5g	USA,Nsc,Sgs	BF314, BF502, BF505, BF507, BF562++
2N4135	Si-N	VHF/UHF/ZF, 30V, 0,03A, 0,2W, >425MHz	5g	USA,Nsc,Sgs	BF314, BF502, BF505, BF507, BF562++
2N4136	Ge-N/P	=2N2430+2431 gep		Amp,Phc	—
2N4137	Si-N	SS, 40V, 0,2A, 0,36W, <15/20ns	2a	USA,Sgs	BSS10..11, BSX19..20, 2N2368..69(A),++
2N4138	Si-N	Chopper, 30V, 0,1A, 0,3W, >20MHz	2e	Tdy,Tix	2N2432
2N4139	N-FET	Uni, ra, 50V, Idss>8mA Up<8V	2b	USA,Mic	BFW10, 2N5363
2N414(A,B,C)	Ge-P	NF/HF, 30V, 0,4A, 0,2W	2a	USA	ASY76..77
2N4140	Si-N	Uni, 60V, 0,2A, 0,3W, <50/310ns, B>40	8e	USA,Mic,Nsc	BC337A BC637, BSV59, 2N2221..22(A)++
2N4141	Si-N	=2N4140: B>100	8a		BC337A, BC637, BSV59, 2N2221..22(A)++
2N4142	Si-P	Uni, 60V, 0,2A, 0,3W, <50/110ns, B>40	8a	USA,Mic,Nsc	BC327A BC638, BSW24, 2N2906..07(A)++
2N4143	Si-P	=2N4142: B>100	8a		BC327A, BC636, BSW24, 2N2906..07(A)++
2N4144	50Hz-Thy	15V, 0,25A(Tc=75°), Igt/Ih<1/<5mA	2a	Sem,Tra,Uni	(2N1595A TAG2-50, MCR1906-3,++)
2N4145	50Hz-Thy	=2N4144: 30V	2a		(2N1595A TAG2-50, MCR1906-3,++)
2N4146	50Hz-Thy	=2N4144: 60V	2a		(2N1596A, TAG2-100, MCR1906-3,++)
2N4147	50Hz-Thy	=2N4144: 100V	2a		(2N1596A, TAG2-100, MCR1906-3,++)
2N4148	50Hz-Thy	=2N4144: 150V	2a		(2N1597A, TAG2-200, MCR1906-4,++)
2N4149	50Hz-Thy	=2N4144: 200V	2a		(2N1597A, TAG2-200, MCR1906-4,++)
2N415(A)	Ge-P	NF/HF, 30V, 0,4A, 0,2W	2a	USA	ASY76..77
2N4150	Si-N	S-L, 100V, 5A, 8,75W(Tc=25°), >15MHz	2e	USA,Sgs	BFT33..34, BUX34, BUY80, 2N5338..39
2N416	Ge-P	NF/HF, 30V, 0,4A, 0,2W	2a	USA	ASY76..77
2N417	Ge-P	NF/HF, 30V, 0,4A, 0,2W	2a	USA	ASY76..77
2N418	Ge-P	S-L, 100V, 5A, 25W(Tc=45°)	23a	USA	AL102..103, AUY28, 2N1542..43,++
2N419	Ge-P	S-L, 55V, 3A, 25W(Tc=45°)	23a	USA	AD149, AUY19..20, 2N2144..46,++
2N4199	F-Thy	300V, 5A(Tc=65°), Igt/Ih<50/3mA, <20µs	21b	Mot,Ssi	(T6F300C, TAG15S-400, C234D, MCR1718-5)
2N42	Ge-P	NF/HF, 30V, 300mA, 0,05W	2a	Cbs	(AC125..126, AC151, ASY26..27)
2N420	Ge-P	S-L, 65V, 5A, 25W(Tc=45°)	23a	USA	AL102..103, AUY28, 2N1546..48,++
2N4200	F-Thy	=2N4199: 400V	21b		(T6F400C, TAG15S-400, C234D, MCR1718-6)
2N4201	F-Thy	=2N4199: 500V	21b		(T6F500C, TAG15S-500, C234E, MCR1718-7)
2N4202	F-Thy	=2N4199: 600V	21b		(T6F600C, TAG15S-600, C234M, MCR1718-8)
2N4203	F-Thy	=2N4199: 700V	21b		(T6F700C, TAG15S-700, T12F700, 2N691S)
2N4204	F-Thy	=2N4199: 800V	21b		(T6P800C, TAG15S-800, T12F800, 2N692S)
2N4205	F-Thy	=2N4199: 900V	21b		(TAG15S-900, T12F900, TAG35S-900)
2N4206	F-Thy	=2N4199: 1000V	21b		(TAG15S-1000, T12F1000, TAG35S-1000)
2N4207	Si-P	S, 6V, 0,05A, 0,35W, <25/25ns	2a	USA,Sgs	BSX38
2N4208	Si-P	S, 12V, 0,05A, 0,35W, <25/30ns	2a	USA,Mot,Sgs	BSX36
2N4209	Si-P	S, 15V, 0,05A, 0,35W, <25/30ns	2a	USA,Mot,Sgs	BSX36
2N420A	Ge-P	=2N420: 90V	23a		AL102..103, AUY26, 2N1547..48,++
2N421	Ge-P	NF/S-L, 65V, 5A		Ben	—
2N4210	Si-N	S-L, 80/60V, 20A, 100W(Tc=60°), >10MHz	49m	USA,Tix	2N2815..22
2N4211	Si-N	=2N4210: 100/80V	49m		2N2815..18, 2N2820..22
2N4212	50Hz-Thy	25V, 1,6A, Igt/Ih<0,1/3mA	2e	Mot,Sgs,Teg	2N2322, 2N6332, TAG615-100 (MCR606-2)
2N4213	50Hz-Thy	=2N4212: 50V	2e		2N2323, 2N6333, TAG615-100 (MCR606-2)
2N4214	50Hz-Thy	=2N4212: 100V	2a		2N2324, 2N6334, TAG615-100 (MCR606-3)
2N4215	50Hz-Thy	=2N4212: 150V	2e		2N2325, 2N6335, TAG615-200, (MCR606-4)
2N4216	50Hz-Thy	=2N4212: 200V	2e		2N2326, 2N6335, TAG615-200, (MCR606-4)
2N4217	50Hz-Thy	=2N4212: 250V	2a		2N2327, 2N6336, TAG815-300, (MCR606-5)
2N4218	50Hz-Thy	=2N4212: 300V	2e		2N2328, 2N6336, TAG815-300, (MCR606-5)
2N4219	50Hz-Thy	=2N4212: 400V	2e		2N2329, 2N6337, TAG615-400, (MCR606-6)
2N422	Ge-P	NF, 35V, 0,1A, 0,15W	2a	USA	AC125..126, AC151, 2SB54, 2SB56

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2N4220(A)	N-FET	Uni, sym, 30V, Idss>0,5mA, Up<4V	5m	USA,EUR	BFS70, 2N3821, 2SK104, 2SK301
2N4221(A)	N-FET	Uni, sym, 30V, Idss>2mA, Up<6V	5m	USA,EUR	BFS71, 2N3822, 2N4341, 2N5381, 2N5458
2N4222(A)	N-FET	Uni, sym, 30V, Idss>5mA, Up<8V	5m	USA,EUR	BF244..245, BFS72, 2N3823, 2N5459
2N4223	N-FET	VHF-V/M, sym, 30V, Idss>3mA, Up<8V	5m	USA,Mot,Tix	BF244..245
2N4224	N-FET	VHF-V/M, sym, 30V, Idss>2mA, Up<8V	5m	USA,Mot,Tix	BF244..245
2N4225	Si-N	S, 80V, 3A, 5W(Tc=25°), <35/75ns	2a	Ker,Sol,Ssi	2N3507
2N4226	Si-N	=2N4225: 100V	2a		—
2N4227	Si-N	NF-Tr, 80V, 0,2A, 0,3W, <50/310ns	8a	Idi,Nsc,Sem	BC337A, BC637, BSV59, 2N2221..22(A)++
2N4228	Si-P	NF-Tr, 80V, 0,2A, 0,3W, <50/110ns	8a	Idi,Nsc,Sam	BC327A, BC638, BSW24, 2N2906..07(A)++
2N422A	Ge-P	=2N422: 0,2A, 0,185W	2a		AC125..126, AC151, 2SB54, 2SB56
2N4231	Si-N	NF/S-L, 50V, 3A, 35W, >4MHz	22a	USA,Mot,Tix	BD241, BD535, BD539A, 2N3054, ++
2N4231A	Si-N	=2N4231: 5A, 75W	22a		BD243, BD949, BD539A, 2N3054, ++
2N4232	Si-N	=2N4231: 70V	22a		BD241A, BD537, BD539B, 2N3054, ++
2N4232A	Si-N	=2N4231: 5A, 75W	22a		BD243A, BD951, BD539B, 2N3054, ++
2N4233	Si-N	=2N4231: 90V	22a		BD241B, BD937, BD539C, 2N3054, ++
2N4233A	Si-N	=2N4231: 90V	22a		BD243B, BD953, BD539C, 2N3054, ++
2N4234	Si-P	NF/S, 40V, 3A, 1W, >3MHz	2a	USA,Mot,Mic	BFT35..37, BSS46, 2N6190..93
2N4234	Si-P			Sgs,Tix,++	—
2N4235	Si-P	=2N4234: 80V	2a		BFT35..37, BSS46, 2N6190..93
2N4236	Si-P	=2N4234: 60V	2a		BFT35..37, BSS46, 2N6190..93
2N4237	Si-N	NF/S, 50V, 3A, 1W, >2MHz	2a	=2N4234	BFT32..34, BSS63..64, 2N5338..39
2N4238	Si-N	=2N4237: 60V	2a		BFT32..34, BSX63..64, 2N5338..39
2N4239	Si-N	=2N4238: 100V	2a		BFT33..34, BSX64, 2N5338..39, 2SC2214
2N424(A/1)	Si-N	NF/S-L, -/80V, 3A, 65W		USA,Tix	2N1722..23,(BD241B, BD537, BD937,++)
2N4240	Si-N	S-L, 500/300V, 2A, 35W, >15MHz	22a	Mot,Rca,Sem	BUW40A,B, BUX84, 2N3585, 2SC3169, ++
2N4240	Si-N			Tho,Tix	—
2N4241(MP)	Ge-P	NF-L, 32,5A, 37W	23a	USA	AL102..103, AUY28, 2N3811..18,++
2N4242	Ge-P	NF/S-L, 80, 10A, 106W, B>40	23a	Csr,Sem	2N1559..80, 2N2289..90, 2N2292..93,++
2N4243	Ge-P	=2N4242: 60V	23a		2N1558..80, 2N2289..90, 2N2292..93,++
2N4244	Ge-P	=2N4242: 40V	23a		2N1557..60, 2N2288..90, 2N2291..93,++
2N4245	Ge-P	=2N4242: B>80	23a		2N1559..60, 2N2269..90, 2N2292..93,++
2N4246	Ge-P	=2N4242: 80V, B>80	23a		2N1558..80, 2N2269..90, 2N2292..93,++
2N4247	Ge-P	=2N4242: 40V, B>80	23a		2N1557..80, 2N2288..90, 2N2291..93,++
2N4248	Si-P	Uni, 40V, 0,1A, 0,2W, B>50	6a	USA,Mic,Sgs	BC415..416, BC560, 2SA970, 2SA1137,++
2N4249	Si-P	=2N4248: 80V, B>100	8a		2SA970, 2SA1049, 2SA1136..37
2N425	Ge-P	NF/S, 30V, 0,4A, 0,15W, B>20	2a	USA,Tix	ASY76..77
2N4250	Si-P	=2N4248: B>250	6a		BC415..416, BC560, 2SA970, 2SA1137,++
2N4250A	Si-P	=2N4246: 80V, B>250	6a		2SA970, 2SA1049, 2SA1138..37
2N4251	Si-N	SS, RadH, 15V, 0,1A, 0,25W, <20/60ns	2a	Fch,Ssi	—
2N4252	Si-N	AM/FM-V/M/O, 30V, 0,05A >600MHz, B>50	5g	USA,Tix	BF240..241, BF254..255, BF594..595,++
2N4253	Si-N	=2N4252: B>30	5g		BF240..241, BF254..255, BF594..595,++
2N4254	Si-N	=2N4252: 0,25W	7c		BF240..241, BF254..255, BF594..595,++
2N4255	Si-N	=2N4252 0,25W, B>30	7c		BF240..241, BF254..255, BF594..595,++
2N4256	Si-N	S, 30V, 0,1A, 0,36W, 200MHz, 4/40ns	7c	Gen,Sem,Spr	BSS11..12, BSX19..20, 2N2368..69(A),++
2N4257(A)	Si-P	S, 6V, 0,05A, 0,2W, >500MHz	8a	USA,Nsc,Sgs	BSX38
2N4256(A)	Si-P	S, 12V, 0,05A, 0,2W, >700MHz	6a	USA,Nsc,Sgs	BSX38
2N4259	Si-N	UHF, 40V, 0,175W, 1GHz	5g	USA,Nsc,Rca	BF377..378, BF689, BF763, 2N2657, ++
2N426	Ge-P	=2N425 B>30	2a	USA,Tix	ASY76..77
2N4260	Si-P	SS, 15V, 0,03A, 0,2W, >1,6GHz, 1,5/2ns	5g	USA,Mot,Tix	—
2N4261	Si-P	=2N4280: >2GHz	5g		—
2N4262	Si-N	HF-Tr/E, 25V, 0,2A, >900MHz	49a	Mot,Sty	—
2N4263	Si-N	=2N4262	49a		—
2N4264	Si-N	S, 30V, 0,2A, 0,625W, <23/35ns, B>40	7e	Fch,Mot,Spr	BSS10..11, BSX19..20, 2N2368..69(A),++
2N4265	Si-N	=2N4264: B>100	7e		BSS10..11, BSX19..20, 2N2368..69(A),++
2N4266	Si-N	=2N4264: B=40..400	7e		BSS10..11, BSX19..20, 2N2368..69(A),++
2N4267	MOS-P-FET-e	S, 30V, Idss<1nA, Up<6V	5(DGsubS)	Fch,Isi,Tdy	—
2N4268	MOS-P-FET-e	S, 30V, Idss<1nA, Up<8V	5(DGsubS)	Fch,Isi,Tdy	—
2N4269	Si-N	Nix, 200V, 0,03A, 0,36W	2a	Csr,Sem,Tra	BF298..299, BF422, 2SC3467
2N427	Ge-P	=2N425: B>40	2a		ASY76..77
2N4270	Si-N	=2N4269: 0,2W	2a		BF258..259, BF658..659, 2N5058..59,++
2N4271	Si-N	S, 175V, 1A, 5W(Tc=100°), >20MHz	2a	USA	BSS46..49, BUX50..52, 2N3439..40,++
2N4272	Si-N	S, 175V, 2,5A, 5W(Tc=100°), >10MHz	2a	USA	BUX50..52, 2SC1651..F1388962, 2SD625
2N4273	Si-N	S-L, 175V, 2,5A, 25W, >10MHz	22a	USA	BD241F, BUX67, 2SD386(A), 2SD1138, ++
2N4274	Si-N	SS, 30V, 0,1A, 0,2W, >400MHz, <12/12ns	6a	USA,Nsc,Sgs	BSV91..92, BSX92..93, 2N2368..69(A),++
2N4275	Si-N	=2N4274: 40V	8a		BSV91..92, BSX92..93, 2N2368..69(A),++
2N4276	Ge-P	NF/S-L, 30V, 60A, 170W, B>60	23a	Gpd,Mot	2N5435..40

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2N4277	Ge-P	=2N4276: B>120	23a		2N5435..40
2N4278	Ge-P	=2N4276: 45V	23a		2N5435..40
2N4279	Ge-P	=2N4276: 45V, B>120	23a		2N5435..40
2N428	Ge-P	=2N425: B>60	2a	USA,Tix	ASY76..77
2N4280	Ge-P	=2N4276: 60V	23a		2N5435..40
2N4281	Ge-P	=2N4276: 60V, B>120	23a		2N5435..40
2N4282	Ge-P	=2N4276: 75V	23a		2N5435..40
2N4283	Ge-P	=2N4276: 75V, B>120	23a		2N5435..40
2N4284	Si-P	NF, sym, 25/25/25V, 0,05A, 0,25W	10b	Nsc,Pih	—
2N4285	Si-P	=2N4284: 35/35/35V	10b		—
2N4286	Si-N	NF, 30V, 0,05A, 0,25W	10b	Nsc,Pih	BC186, BC183, BC238, BC548, ++
2N4287	Si-N	=2N4286: 45V	10b		BC167, BC182, BC237, BC547, ++
2N4288	Si-P	NF, ra, 30V, 0,05A, 0,25W, 150MHz	10b	Nsc,Pih	BC214, BC259, BC309, BC559, ++
2N4289	Si-P	=2N4288: 60V	10b		2SA872(A), 2SA970, 2SA1049, 2SA1137, ++
2N428A	Ge-P	=2N425: B>60	2a		ASY76..77
2N29	Si-N			Gen	—
2N4290	Si-P	NF, ra, 30V, 0,2A, 0,25W, 150MHz	10b	Mic,Nsc,Pih	BC214, BC259, BC309, BC559, ++
2N4291	Si-P	=2N4290: 40V	10b		BC415..416, BC560, 2SA872(A), 2SA970++
2N4292	Si-N	VHF/ZF, 30V, 0,06A, 0,2W, 730MHz	10b	Mic,Nsc,Pih	BF225, BF314, BF502, BF505, BF507++
2N4293	Si-N	VHF/ZF, 30V, 0,06A, 0,2W, 730MHz	10b	Mic,Nsc,Pih	BF225, BF314, BF502, BF505, BF507++
2N4294	Si-N	S, 30V, 0,2A, 0,2W, <21/30ns	10b	Mic,Nsc	BSS10..11, BSX19..20, 2N2368..69(A), ++
2N4295	Si-N	S, 40V, 0,2A, 0,2W, <24/30ns	10b	Mic,Nsc	BSS10..11, BSX19..20, 2N2368..69(A), ++
2N4296	Si-N	S-L, 350/250V, 1A, 20W, >20MHz, B>50	22a	USA,Rca	BUW40(A,B), TIP47..50, 2N4240, ++
2N4297	Si-N	=2N4296: B>75	22a		BUW40(A,B), TIP47..50, 2N4240, ++
2N4298	Si-N	=2N4296: 500/350V, B>25	22a		BUW40A,B, BUX84, TIP50, 2N4240, ++
2N4299	Si-N	=2N4296: 500/350V, B>50	22a		BUW40A,B, BUX84, TIP50, 2N4240, ++
2N43(A)	Ge-P	NF/HF, 45V, 0,3A, 0,15W	1a	USA	ASY48, ASY76..77, 2N1189..1190
2N430	Si-N			Gen	—
2N430+A13718	Si-N	NF/S-L, 100V, 2A, 15W(Tc=100°), >30MHz	2a	USA,Tix	BUX49, BUY41, 2SC1860
2N4301	Si-N	S-L, 100/60V, 10A, 50W(Tc=100°), >40MHz	49m	USA,Tix	2N5286..89, 2N5542
2N4302	N-FET	Uni, ra, 30V, Idss>0,5mA, Up<4V	8b	USA,Mic,Nsc	BFS70, 2N3821, 2N4220, 2SK104, 2SK301
2N4303	N-FET	Uni, ra, 30V, Idss>4mA, Up<6V	8b	USA,Mic,Nsc	BFS80, BFW11, 2N4416, 2N5362, 2N5245
2N4304	N-FET	Uni, ra, 30V, Idss>0,5mA, Up<10V	8b	USA,Mic,Nsc	2N3365
2N4305	Si-N	NF/S, 120V, 5A, 1,5W, <140/400ns, B>50	2a	USA,Tix	BFT34, BUX34, BUY60, 2N4395..97
2N4306	Si-N	=2N4305: 30W	≈55		—
2N4307	Si-N	=2N4305: 100V	2a		BFT33, BUX34, BUY60, 2N4395..97
2N4308	Si-N	=2N4307: 30W	≈55		—
2N4309	Si-N	=2N4305: B>40	2a		BFT34, BUX34, BUY60, 2N4895..97
2N431	Si-N			Gen	—
2N4310	Si-N	=2N4309: 30W	≈55		—
2N4311	Si-N	=2N4305: 100V, B>40	2a		BFT33, BUX34, BUY60, 2N4895..97
2N4312	Si-N	=2N4311: 30W	≈55		—
2N4313	Si-P	S, 12V, 0,1A, 0,2W, <25/35ns	8a	USA,Mic,Nsc	BSX36
2N4314	Si-P	NF/S, 90V, 1A, 1W, >60MHz	2a	USA,Nsc,Rca	BCX60, BSS17, BSV17, 2N3634..37
2N4315	Si-N	Dual, 30V, 0,05A, 0,4W, >100MHz	TO-77	Amp	2N3409..11
2N4316	50Hz-Thy	100V, 8A(Tc=85°), Igt/Ih<15/<25mA	22a	Fch,Ssi	BStC0506, TAG671-100, TAG676-100
2N4317	50Hz-Thy	=2N4316: 200V	22a		BStC0513, TAG671-200, TAG676-200
2N4318	50Hz-Thy	=2N4316: 300V	22a		BStC0528, TAG671-300, TAG676-300
2N4319	50Hz-Thy	=2N4316 400V	22a		BStC0526, TAG671-400, TAG676-400
2N432	Si-N	30V, 0,1A, 0,15W, >10MHz	2a	Gen	—
2N4320	GTO-Thy	30V, 0,25A(Tc=75°), Igt/Ih<0,5/<3mA	2	Sem,Sld	—
2N4321	GTO-Thy	=2N4320: 60V	2		—
2N4322	GTO-Thy	=2N4320: 100V	2		—
2N4323	GTO-Thy	=2N4320: 150V	2		—
2N4324	GTO-Thy	=2N4320: 200V	2		—
2N4325	GTO-Thy	=2N4320: 250V	2		—
2N4326	GTO-Thy	30V, 0,39A(Tc=75°), Igt/Ih<0,5/<3mA	2	Sem,Sld	—
2N4327	GTO-Thy	=2N4326: 60V	2		—
2N4328	GTO-Thy	=2N4326: 100V	2		—
2N4329	GTO-Thy	=2N4326: 150V	2		—
2N433	Si-N	30V, 0,1A, 0,15W, >10MHz	2a	Gen	—
2N4330	GTO-Thy	=2N4326: 200V	2		—
2N4331	GTO-Thy	=2N4326: 250V	2		—
2N4333	N-FET	Uni, ra, 50V, Idss>0,2mA, Up<1V	2b	USA,EUR	BFW13
2N4339	N-FET	Uni, ra, 50V, Idss>0,5mA, Up<1,8V	2b	USA,EUR	2N5358, 2SK83, 2SK193, 2SK195, 2SK238
2N434	Si-N			Gen	—

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2N4340	N-FET	Uni,ra,50V,Idss>1,2mA,Up<3V	2b	USA,EUR	BFW12,2N5484
2N4341	N-FET	Uni,ra,50V,Idss>3mA,Up<6V	2b	USA,EUR	BF256,BFS71,3N3822,2N4221,2N5381++
2N4342	P-FET	Uni,ra,25V,Idss>4mA,Up<5,5V	8b	USA,Mot,Nsc	2N5118
2N4343	P-FET	Uni,ra,25V,Idss>10mA,Up<10	8b	Fch,Isi	BFT11
2N4346	Ge-P	TV-HA,320/60V,10A,5W(Tc=80°)	23a	Gpd,Rca,Stc	AU106,AU109,AU111..112,2N5325
2N4347	Si-N	NF/S-L,140V,5A,100W,>0,2MHz	23a	USA,EUR	BDX12,2N5760,2SD732..733,2SD551,++
2N4348	Si-N	NF/S-L,140V,10A,120W,>0,2MHz	23a	USA,EUR	BDX51,2N5634,2SD732..733,2SD551,++
2N4349	Si-N	NF/S,65V,2A,7W(Tc=25°),<55/165ns	2a	Sca,Ssi,Tra	BSS14,2N5262
2N4350	Si-N	NF/S,65V,0,35A,7W(Tc=25°),>300MHz	2a	Sem,Sca,Ssi	BSS27,BSV95,2N3722..23,2SC1386,++
2N4351	MOS-N-FET-e	S,30V,Idss<10nA,Up<5V	5n	Gie,Isi,Mot	—
2N4352	MOS-N-FET-e	S,30V,Idss<10nA,Up<5V	5n	Gie,Mot	—
2N4353	MOS-N-FET-e	S,30V,Idss<5nA,Up<5V	5(DGsubS)	Gie,Isi	—
2N4354	Si-P	NF/S,60V,0,5A,0,35W,<100/400ns	8a	USA,Nsc,Sgs	BC327A,BC638,BSW24,2N2906..07(A)++
2N4355	Si-P	NF/S,60V,0,5A,0,35W,<100/400ns	8a		BC327A,BC638,BSW24,2N2906..07(A)++
2N4356	Si-P	NF/S,60V,0,5A,0,35W,<100/400ns	8a		BC640,BCX39,2SB647,2N4029
2N4357	Si-P	Vid,240V,0,05A,0,4W,>40MHz	2a	Fch,Sca,Sgs	BF438..437,BF492..493,2SA1371,++
2N4358	Si-P	=2N4357:0,7W	2a		BFQ38..37,BFT44..45,2SB606,++
2N4359	Si-P	Uni,45V,0,05A,0,36W,>20MHz	2a	USA,Sgs	BC212,BC257,BC307,BC557,++
2N4380	P-FET	Uni,ra,20V,Idss>3mA,Up<10V	8b,7c	USA,Mrc,Mot	—
2N438(A)	Ge-N	NF/S,30V,0,4A,0,1..0,15W,>2,5MHz	2a(B=case)	USA,Tix	ASY73..75
2N4381	P-FET	Uni,ra,25V,Idss>3mA,Up<5V	2a	Fch,Nsc,Sol	2N5461,2N5464
2N4382	P-FET	Uni,ra,25V,Idss>10mA,Up<9V	2a	Fch,Nsc,Sol	BFT11,2N4343
2N4383	Si-N	Uni,ra,40V,0,8A,0,8W,>120MHz	2a	USA,Nsc	(BC140..141,BC300..302,2N3053,++)
2N4364	Si-N	=2N4383:0,5W	2a		(BC337,BC635,BC637,BC639,++)
2N4385	Si-N	Uni,ra,40V,0,8A,0,8W,>120MHz	2a		(BC140..141,BC300..302,2N3053,++)
2N4386	Si-N	=2N4365:0,5W	2a		(BC337,BC635,BC637,BC639,++)
2N4387	Si-P	NF-L,40V,2A,20W	22a	USA,Tix	BD240,BD242,BD934,2N3740..41,++
2N4388	Si-P	=2N4387:60V	22a		BD240A,BD242A,BD938,2N3740..41,++
2N4389	Si-P	S,12V,0,1A,0,2W,<25/105ns	8a	Csr,Fch,Sgs	BSX38,2N4313
2N439(A)	Ge-N	NF/S,30V,0,4A,0,1..0,15W,>5MHz	2a(B=case)	USA,Tix	ASY73..75
2N4390	Si-N	Nix,120V,0,5W,>50MHz	2a	Sca,Sgs	BF297..299,BSS38,BSX21,2SC3467,++
2N4391	N-FET	S,Chopper,40V,Idss>50mA,Up<10V	2b	USA,EUR	BFS74,BFS77,BSV78,2N3970,2N4859++
2N4392	N-FET	S,Chopper,40V,Idss>25mA,Up<5V	2b	USA,EUR	2N3971,2N5434
2N4393	N-FET	S,Chopper,40V,Idss>5mA,Up<3V	2b	USA,EUR	2N3972
2N4395	Si-N	NF/S-L,60V,5A,62W,>4MHz	23a	USA	BD245A,BDV91,BDX91,2N4914..15,++
2N4396	Si-N	=2N4395:60V	23a		BD245B,BDV93,BDX93,2N5758..60,++
2N4397	Si-N	VHF,re,40V,0,2W,>600MHz	5k	Sty	BF314,BF502,BF505,BF507,BF562++
2N4398	Si-P	NF/S-L,40V,30A,200W,>4MHz	23a	USA,Mot,Sgs	MJ4502
2N4398	Si-N			Tix,Tos,++	—
2N4399	Si-P	=2N4398:60V	23a		MJ4502
2N44(A)	Ge-P	NF/HF,45V,0,3A,0,15W	1a	USA	ASY48,ASY76..77,2N1189..1190
2N440(A)	Ge-N	NF/S,30V,0,4A,0,1..0,15W,>10MHz	2a(B=case)	USA,Tix	ASY73..75
2N4400	Si-N	Uni,60V,0,6A,0,625W,<35/255ns,B>50	7e	USA,Gen,Mot	BC337A,BC637,BC639,2N2221..22(A)++
2N4400	Si-N			Nsc,Phi,++	—
2N4401	Si-N	=2N4400:B>100	7e		BC337A,BC637,BC639,2N2221..22(A)++
2N4402	Si-P	Uni,40V,0,6A,0,625W,<35/255ns,B>50	7e	USA,Gen,Mot	BC327,BC638,BC640,2N2906..07(A),++
2N4402	Si-P			Nsc,Phi,++	—
2N4403	Si-P	=2N4402:B>100	7e		BC327,BC638,BC840,2N2906..09(A),++
2N4404	Si-P	NF/S,60V,1A,1,25W,<40/210ns,B>40	2a	USA,Mot	BSV82,BSW40,2N4031,2N4033,2N4038
2N4405	Si-P	=2N4404:B>100	2a		BSV82,BSW40,2N4031,2N4033,2N4036
2N4406	Si-P	NF/S,80V,2A,1,25W,<75/225ns,B>25	2a		BSV82,2N6303
2N4407	Si-P	=2N4406:B>75	2a		BSV82,2N6303
2N4409	Si-N	Nix,80V,0,25A,0,625W,>60MHz	7e	USA,Mot,Tix	BF391,BFP22,MPS-A43,2SC1670,++
2N441	Ge-P	NF/S-L,40V,15A,150W	38a	USA,Mot	2N1980..82,2N2077..78,2N2491,++
2N4410	Si-N	=2N4409:120V	7e		BF391,BFP22,MPS-A43,2SC1670,++
2N4411	Si-P	HF,15V,0,025A,0,15W,>400MHz	5g	Idi	BF324,BF414,BF506,BF709,BF914++
2N4412	Si-P	NF,40V,0,6A,0,6W,>20MHz,B>100	2a	Sem,Spr	BC160..161,BC303..304,2N2904..05,++
2N4412A	Si-P	=2N4412:60V	2a		BC161,BC303..304,2N2904..05A,++
2N4413(A)	Si-P	=2N4412(A):0,4W	2a		BC327A,BC638,BC640,2N2906..07A,++
2N4414	Si-P	=2N4412:B>40	2a		BC160..161,BC303..304,2N2904..05,++
2N4414A	Si-P	=2N4412:60V,B>40	2a		BC161,BC303..304,2N2904..05A,++
2N4415(A)	Si-P	=2N4414(A):0,4W	2a		BC327A,BC638,BC840,2N2906..07A,++
2N4416	N-FET	VHF/UHF,ra,30V,Idss>5mA,Up<6V	5k	USA,EUR	BF256,BFS60,BFW11,2N5245,2N5398
2N4416A	N-FET	=2N4416:35V	5k		BF256,BFS60,BFW11,2N5245,2N5398
2N4417(A)	N-FET	=2N4416(A):	24e	Mrc,Sol,Uca	BF256,BFS60,BFW11,2N5245,2N5398
2N4418	Si-N	S,40V,0,2A,0,38W,>500MHz,<22/26ns	7a	Itt,Spe	BSS10..11,BSX19..20,2N2368..69(A),++

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2N4419	Si-N	S, 30V, 0,2A, 0,36W, >400MHz, <24/30ns	7a	Itt,Spe	BSS 10..11, BSX 19..20, 2N2368..69(A),++
2N442	Ge-P	=2N441: 50V	38a	USA, Mot	2N1980..82, 2N2077, 2N2081, 2N2491,++
2N4420	Si-N	S, 40V, 0,2A, 0,36W, >350MHz, <13/25ns	7a	Itt,Spe	BSS 10..11, BSX 19..20, 2N2368..69(A),++
2N4421	Si-N	S, 30V, 0,2A, 0,36W, >300MHz, <22/30ns	7a	Itt,Spe	BSS 10..11, BSX 19..20, 2N2368..69(A),++
2N4422	Si-N	S, 40V, 0,2A, 0,36W, >350MHz, <25/35ns	7a	Itt,Spe	BSS 10..11, BSX 19..20, 2N2368..69(A),++
2N4423	Si-P	S, 12V, 0,2A, 0,36W, >400MHz, <45/55ns	8a	Gen,Nsc,Tix	BSX 36, 2N4313
2N4424	Si-N	NF/S, 60V, 0,5A, 0,36W	7c	USA,Gen,Tho	BC 337A, BC 637, BC 640, 2SD667, ++
2N4425	Si-N	=2N4424: 0,56W	7c°		BC 337A, BC 637, BC 640, 2SD667, ++
2N4427	Si-N	VHF-Tr/E, 40V, 0,4A, 1W, PQ=0,4W(400MHz)	2a	USA,EUR	BFR 98, BFS 50, MRF 515, MRF 629, 2N3948
2N4428	Si-N	UHF-Tr/E, 55V, 0,4A, PQ=0,75W(500MHz)	2a	USA,Mot,Tho	BFR 97, 2N3666
2N4429	Si-N	UHF-Tr/E, 55V, 0,425A, PQ>1W(1GHz)	55r	USA,Tho,Tix	BLX 91
2N443	Ge-P	=2N441: 80V	38a	USA, Mot	2N1981..82, 2N2075..76, 2N2491,++
2N4430	Si-N	UHF-L, 55V, 1A, PQ>2,5W(1GHz)	55r	USA,Tho,Tix	BLW 98, BLX 98
2N4431	Si-N	UHF-L, 55V, 2A, PQ>5W(1GHz)	55r	USA,Tho,Tix	2SC3141
2N4432(A)	Si-N	Uni, 50V, 0,2A, 0,6W, 250MHz	2a	Tho,Tix	BC 140..141, BC 300..302, 2N2218..19,++
2N4433	Si-N	HF, 50V, 0,03A, 0,145W, 200MHz	5k	Phi,Sty	BF 240..241, BF 254..255, BF 594..595,++
2N4434	Si-N	HF, 30V, 0,03A, 0,145W, 300MHz	5k	Phi,Sty	BF 240..241, BF 254..255, BF 594..595,++
2N4435	Si-N	HF, 30V, 0,03A, 0,145W, 220MHz	5k	Phi,Sty	BF 240..241, BF 254..255, BF 594..595,++
2N4436	Si-N	Uni, 60V, 0,5A, 0,2W, <60/150ns, B>40	8a	Fch,Sgs	BC 337A, BC 637, BSV 59, 2N2221..22(A)++
2N4437	Si-N	=2N4436: B>100	8a		BC 337A, BC 637, BSV 59, 2N2221..22(A)++
2N4436	Si-N	Vid, 300V, 0,2A, 1W, >30MHz, B>40	2a	Sca,Ssi,Sty	BF 259, BF 659, BFR 59, BFS 89, 2N5055
2N4439	Si-N	=2N4433: B>100	2a		BF 259, BF 659, BFR 59, BFS 89, 2N5058
2N444	Ge-N	NF/S, 15V, 0,025mA, 0,1W, >0,5MHz	2a(B=case)	USA	ASY 28..29, ASY 73..75
2N4440	Si-N	VHF/UHF-L, 65V, 1,5A, PQ>5W(400MHz)	49a	USA,Rca,Mot	—
2N4440	Si-N			Tho,Tix,++	—
2N4441	50Hz-Thy	50V, 5,1A(Tc=73°), Igt/Ih<30/<40mA	16e	Mot	—
2N4442	50HZ-Thy	=2N4441: 200V	16e		—
2N4443	50HZ-Thy	=2N4441: 400V	16e		—
2N4444	50HZ-Thy	=2N4441: 600V	16e		—
2N4445	N-FET	S, Chopper, 25V, 0,4A, Up<10V	2b	Tix,Tdy	—
2N4445A	N-FET	=2N4445: 35V	2b		—
2N4446	N-FET	S, Chopper, 25V, 0,4A, Up<5V	2b	Tix,Tdy	—
2N4446A	N-FET	=2N4446: 35V	2b		—
2N4447	N-FET	S, Chopper, 20V, 0,4A, Up<5V	2b	Tix,Tdy	—
2N4447A	N-FET	=2N4447: 25V	2b		—
2N4448	N-FET	S, Chopper, 20V, 0,4A, Up<5V	2b	Tix,Tdy	—
2N4448A	N-FET	=2N4448: 25V	2b		—
2N4449	Si-N	S, -/15V, 0,2A, 0,3W, <69/20ns	2a	Fch,Ray,Sca	BSS 11..12, BSX 19..20, 2N2368..69(A),++
2N444A	Ge-N	=2N444: 40V, 0,15W	2a(B=case)		—
2N445	Ge-N	NF/S, 15V, 0,05A, 0,1W, >2MHz	2a(B=case)	USA	ASY 28..29, ASY 73..75
2N4450	Si-N	Uni, 80V, 0,5A, 0,36W, 50/125ns	2a	Fch,Mot,Sgs	BC 337A, BC 637, BSV 59, 2N2221..22(A)++
2N4451	Si-P	S, -/12V, 0,1A, 0,3W, <65/95ns	2a	Fch,Sgs	BSX 36, 2N4313, 2N3209, 2N4125..28,++
2N4452	Si-P	S, 45V, 0,5A, 0,35W, <95/210ns	2a	Fch,Sca,Sgs	BC 327, BC 638, BSW 24, 2N2906..07(A),++
2N4453	Si-P	Uni, 25V, 0,2A, 0,3W, 30/60ns	2a	Fch,Mot,Sgs	BC 308, BC 558, BSW 24, 2N3250..51(A),++
2N445A	Ge-N	=2N445: 30V, 0,15W	2a(B=case)		ASY 28, ASY 73..75
2N446	Ge-N	NF/S, 15V, 0,025A, 0,1W, >5MHz	2a(B=case)	USA	ASY 28..29, ASY 73..75
2N446A	Ge-N	=2N446: 30V, 0,05A, 0,15W	2a(B=case)		ASY 28, ASY 73..75
2N447	Ge-N	NF/S, 15V, 0,05A, 0,1A, >9MHz	2a(B=case)	USA	ASY 28..29, ASY 73..75
2N447A	Ge-N	=2N447: 30V, 0,15W	2a(B=case)		ASY 28, ASY 73..75
2N447B	Ge-N	=2N447: 25V, 0,15W	2a(B=case)		ASY 28..29, ASY 73..75
2N448	Ge-N	HF, 25V, 0,3A, 0,065W, 5MHz	2a	USA	—
2N449	Ge-N	HF, 25V, 0,3A, 0,065W, 5MHz	2a	USA	—
2N45(A)	Ge-P	NF/HF, 45V, 0,01A, 0,15W	1a	USA	ASY 48, 2SB56A
2N450	Ge-P	NF/S, 20V, 0,125A, 0,15W, 10MHz	1a	USA	ASY 26..27, ASY 76..77
2N451	Si-N	NF/S-L, 65V, 5A, 85W		Gen	(BD 245A, BDV 93, 2SD895..896,++)
2N452	Si-N	NF/S-L, 65V, 5A, 85W		Gen	(BD 245A, BDV 93, 2SD895..896,++)
2N453	Si-N	NF/S-L, 30V, 2A, 85W		Gen	(BD 245, BDV 93, 2SD895..896,++)
2N454	Si-N	NF/S-L, 65V, 2A, 85W		Gen	(BD 245A, BDV 93, 2SD895..896,++)
2N456	Ge-P	S-L, 40V, 5A, 50W	23a	USA, Mot,Tix	AL 102..103, AUY 21..22, 2N1529..48,++
2N456A,B	Ge-P	=2N458: 7A, 85..150W	23a		2N2266..93, 2N3611..18
2N457	Ge-P	S-L, 80V, 5A, 50W	23a	USA, Mot,Tix	AL 102..103, AUY 21..22, 2N1545..48,++
2N4576	Si-N	S-L, 100V, 150W			—
2N457A,B	Ge-P	=2N457: 7A, 85..150W	23a		2N2282..93, 2N3615..18
2N455	Ge-P	S-L, 80V, 5A, 50W	23a	USA, Mot,Tix	AL 102..103, AUY 21..22, 2N1546..48,++
2N458A, B	Ge-P	=2N458: 7A, 65..150W	23a		2N2292..93, 2N3615..18
2N459(A)	Ge-P	NF/S-L, 105V, 5A, 106W	23a	USA, Mot	2N1537..36, 2N1547..48, 2N3616, 2N3618

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2N46	Ge-P	NF/HF, 25V, 0,015A, 0,05W		Rca	AC 125..126, AC 151, ASY26..27
2N460	Ge-P	NF/S, 45V, 0,4A, 0,225W, 1,2MHz	2a(B=case)	USA, Mot	2N1189..90, 2SB405ST
2N461	Ge-P	NF/S, 45V, 0,4A, 0,225W, 4MHz	2a(B=case)	USA, Mot	2N1189..90, 2SB405ST
2N462	Ge-P	NF/S, 40V, 0,2A, 0,15W	37e	Etc, Phc	2N1191..94, 2SB56A
2N463	Ge-P	NF/S-L, 60V, 5A, 37W		Wes	(2N1981..82, 2N2075..76, 2N2490..93,++)
2N464	Ge-P	NF, 45V, 0,5A, 0,2W	2a	USA, Mot	2N1189..90, 2SB405ST
2N465	Ge-P	NF, 45V, 0,5A, 0,2W	2a	USA, Mot	2N1189..90, 2SB405ST
2N466	Ge-P	NF, 35V, 0,5A, 0,2W	2a	USA, Mot	AC 128, AC 153, 2N1189..90, 2SB405ST
2N467	Ge-P	NF, 35V, 0,5A, 0,2W	2a	USA, Mot	AC 126, AC 153, 2N1189..90, 2SB405ST
2N468T	Ge-N	NF/S-L, 60V, 3A		Cbs, Gen	—
2N469(A)	Opto				—
2N47	Ge-P	NF, 35V, 0,02A, 0,05W	37d	Phc	AC 125..126, AC 151, ASY26..27
2N470(A)	Si-N	Uni, 15V, 0,025A, 0,2W, >8MHz	2a	USA	BC 168, BC 183, BC 238, BC 548, ++
2N471(A)	Si-N	=2N470: 30V	2a	USA	BC 168, BC 183, BC 238, BC 548, ++
2N472(A)	Si-N	=2N470: 45V	2a	USA	BC 167, BC 182, BC 237, BC 547, ++
2N473(A)	Si-N	Uni, 15V, 0,025A, 0,2W, >8MHz	2a	USA	BC 168, BC 183, BC 238, BC 548, ++
2N474(A)	Si-N	=2N473: 30V	2a	USA	BC 168, BC 163, BC 238, BC 548, ++
2N475(A)	Si-N	=2N473: 45V	2a	USA	BC 167, BC 182, BC 237, BC 547, ++
2N476(A)	Si-N	Uni, 15V, 0,025A, 0,2W, >12MHz	2a	USA	BC 168, BC 183, BC 238, BC 548, ++
2N477(A)	Si-N	=2N476: 30V	2a	USA	BC 168, BC 183, BC 238, BC 548, ++
2N478(A)	Si-N	Uni, 15V, 0,025A, 0,2W, >20MHz	2a	USA	BC 168, BC 183, BC 238, BC 548, ++
2N479(A)	Si-N	=2N478: 30V	2a	USA	BC 168, BC 183, BC 238, BC 548, ++
2N48	Ge-P	NF, 35V, 0,02A, 0,05W	37d	Phc	AC 125..126, AC 151, ASY26..27
2N460(A)	Si-N	=2N478: 45V	2a	USA	BC 167, BC 182, BC 237, BC 547, ++
2N481	Ge-P	HF, 12V, 0,02A, 0,15W, 3MHz	2a	USA	AF 124..127, AF 200
2N462	Ge-P	HF, 12V, 0,02A, 0,15W, 3,5MHz	2a	USA	AF 124..127, AF 200
2N463	Ge-P	HF, 12V, 0,02A, 0,15W, 5,5MHz	2a	USA	AF 124..127, AF 200
2N484	Ge-P	HF, 12V, 0,02A, 0,15W, 10MHz	2a	USA	AF 124..127, AF 200
2N485	Ge-P	HF, 12V, 0,01A, 0,15W, 7,5MHz	2a	USA	AF 124..127, AF 200
2N4851	UJT-P	Ip<2µA, Iv>2mA	5e	Mot, Tix	2N4947, 2N4948, 2N4893
2N4852	UJT-P	=2N4851: Iv>4mA	5e		2N4892
2N4853	UJT-P	=2N4851: Ip<0,4µA, Iv>6mA	5e		—
2N4854	Si-N/P	NPN+PNP, 60V, 0,6A, 0,6W, >200MHz, B>100	TO-77	Mot, Sgs, Tix	BFX79
2N4855	Si-N/P	=2N4854: B>40	TO-77		BFX79
2N4856(A)	N-FET	S, sym, 40V, Idss>50mA, Up<10V	2b	USA, EUR	BFS 74, BFS 77, BSV 78, 2N3970, 2N4391
2N4957(A)	N-FET	S, sym, 40V, Idss>20mA, Up<6V	2b	USA, EUR	BFS 75, BFS 78, BSV 79
2N4856(A)	N-FET	S, sym, 40V, Idss>8mA, Up<4V	2b	USA, EUR	BFS 76, BFS 79, BSV 80, 2N4093
2N4859(A)	N-FET	S, sym, 30V, Idss>50mA, Up<10V	2b	USA, EUR	BFS 74, BFS 77, BSV 78, 2N3970, 2N4391
2N468	Ge-P	HF, 12V, 0,01A, 0,15W, 12MHz	2a	USA	AF 124..127, AF 200
2N4860(A)	N-FET	S, sym, 30V, Idss>20mA, Up<6V	2b	USA, EUR	BFS 75, BFS 78, BSV 79
2N4861(A)	N-FET	S, sym, 30V, Idss>8mA, Up<4V	2b	USA, EUR	BFS 76, BFS 79, BSV 80, 2N4093
2N4862	Si-N	NF/S, 140V, 2A, 4W(Tc=100°), >50MHz	2a	USA	(BUX 49, BUY 41, 2SC1860)
2N4863	Si-N	NF/S, 140V, 2A, 7W(Tc=25°), >50MHz	2a	USA	(BUX 49, BUY 41, 2SC1860)
2N4864	Si-N	NF/S-L, 140V, 2A, 29W, >50MHz	22a	USA	2SC2529, 2SC2660, 2SD759..760
2N4865	Si-N	S-L, 100/60V, 90A, 350W, >10MHz	49m	USA	2N6309..11
2N4866	Si-N	=2N4865: 140/120V	49m		2N6309..11
2N4867(A)	N-FET	Uni, ra, 40V, Idss>0,4mA, Up<2V	5k	Isi, Tix, ++	2N4339, 2N5358, 2SK83, 2SK193, 2SK195
2N4868(A)	N-FET	Uni, ra, 40V, Idss>3mA, Up<3V	5k	Isi, Tix, ++	BC 264, BF 410, 2SK192, 2SK370
2N4689(A)	N-FET	Uni, ra, 40V, Idss>2,5mA, Up<6V	5k	Isi, Tix	BF256, BFS71, 2N3822, 2N4221, ++
2N487	Ge-P	HF, 18V, 0,025A, 0,1W, >10MHz	2a	USA	AF 124..127, AF 200
2N4870	UJT-P	Ip<5µA, Iv>2mA	7b	Mot, Phi	2N4891
2N4671	UJT-P	=2N4870: Iv>4mA	7b		2N2646
2N4672	Si-P	S, RadH, 12V, 0,05A, 0,3W, <25/30ns	2a	Fch, Sgs	—
2N4873	Si-N	S, RadH, 40V, 0,2A, 0,36W, <20/30ns	2a	Fch, Sgs	—
2N4874	Si-N	VHF/UHF-O/Tr, 30V, 0,2A, 0,72W, >900MHz	2a	Ray, Sca, Tix	BFR38, 2SC1199, 2SC1252, 2SC1385..68
2N4875	Si-N	VHF/UHF-O/Tr, 40V, 0,2A, 0,72W, >600MHz	2a	Ray, Sca, Tix	BFR38, 2SC1199, 2SC1252, 2SC1365..68
2N4878	Si-N	VHF/UHF-O/Tr, 40V, 0,2A, 0,72W, >650MHz	2a	Rsy, Sca, Tix	BFR36, 2SC1199, 2SC1252, 2SC1365..68
2N4877	Si-N	NF/S, 70V, 4A, 10W(Tc=25°), >30MHz	2a	USA, Mot	BUX34, BUY60, 2N5336..39
2N4878	Si-N	=2N4044: 0,5W	TO-71	Isi, Sol, Sty	→2N4044
2N4879	Si-N	=2N4100: 0,5W	TO-71	Isi, Sol, Sty	→2N4100
2N4880	Si-N	=2N4045: 0,5W	TO-71	Isi, Sol, Sty	→2N4045
2N4881	N-FET	S, 300V, Idss>0,4mA, Up<15V	2b	Tdy, Tix, Tsc	2N5543
2N4882	N-FET	S, 300V, Idss>1,5mA, Up<15V	2b	Tdy, Tix, Tsc	2N5543
2N4883	N-FET	S, 200V, Idss>0,4mA, Up<15V	2b	Tdy, Tix, Tsc	2N5542..43
2N4684	N-FET	S, 200V, Idss>1,5mA, Up<15V	2b	Tdy, Tix, Tsc	2N5542..43
2N4885	N-FET	S, 125V, Idss>0,4mA, Up<15V	2b	Tdy, Tix, Tsc	2N5542..43

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2N4886	N-FET	S, 125V, Idss>1,5mA, Up<15V	2b	Tdy,Tix,Tsc	2N5542 .43
2N4888	Si-P	Vid, 150V, 0,05A, 0,3W, >30MHz	8a	Fch,Spe	BF398, BF423, BF435. 437, 2SC1370, ++
2N4889	Si-P	=2N4888: >40MHz	8a		BF398, BF423, BF435. 437, 2SC1370, ++
2N489 494(A)	UJT-P	Ip<12μA, Iv>8mA	5e,2f	Gen,Ssc,Tix	—
2N4890(S)	Si-P	NF/S, 60V, 0,5A, 1W, 35/130ns	2a	USA, Mot	BC161, BC303. 304 2N2904 .05(A), ++
2N4891(L)	UJT-P	Ip<5μA, Iv>2mA	7b	Mot,Tix	2N4870
2N4892(L)	UJT-P	=2N4891: Ip<2μA, Iv>4mA	7b		2N4852
2N4893(L)	UJT-P	=2N4891: Ip<2μA, Iv>2mA	7b		2N4851, 2N4947, 2N4948
2N4894(L)	UJT-P	=2N4891 Ip<1μA, Iv>2mA	7b		2N4949
2N4895	Si-N	S, 120V, 5A, 1W, >50MHz, B>40	2a	USA,Sgs	BFT34, BUX34, BUY60
2N4896	Si-N	=2N4895: >80MHz, B>100	2a		BFT34, BUX34, BUY80
2N4897	Si-N	=2N4895: 150V	2a		BUY60
2N4898	Si-P	NF/S-L, 40V, 1A, 25W, >3MHz	22a	USA,Fch, Mot	BD240, BD242, BDX14, 2N3740 .41, ++
2N4898	Si-P			Rca,Sgs,Tix	—
2N4899	Si-P	=2N4898: 60V	22a		BD240A, BD242A, BDX14, 2N3740..41, ++
2N489B .494B	UJT-P	=2N489..494: Ip<6μA	5e,2f		—
2N489C...494C	UJT-P	=2N489 494: Ip<2μA	5e,2f		2N2647
2N49	Ge-P	NF, 35V, 0,02A, 0,05W	37d	Phc	AC125..126, AC151, ASY26..27
2N4900	Si-P	=2N4898: 60V	22a		BD240B, BD242B, BDX14, 2N3741, ++
2N4901	Si-P	NF/S-L, 40V, 5A, 87,5W, >4MHz, B>20	23a	USA,Fch, Mot	BD246, BDV92, BDX92, 2N5871..72, ++
2N4901	Si-P			Tho,Tix	—
2N4902	Si-P	=2N4901: 60V	23a		BD246A, BDV92, BDX92, 2N5871 72, ++
2N4903	Si-P	=2N4901: 80V	23a		BD246B, BDV94, BDX94, 2N5872, ++
2N4904	Si-P	=2N4901 B>25	23a		BD246, BDV92, BDX92, 2N5871 72, ++
2N4905	Si-P	=2N4901 60V, B>25	23a		BD246A, BDV92, BDX92, 2N5871..72, ++
2N4906	Si-P	=2N4901: C1401580V, B>25	23a		BD246B, BDV94, BDX94, 2N5872, ++
2N4907	Si-P	NF/S-L, 40V, 10A(ss), 150W, 4MHz	23a	USA,Sgs	BD312, BD546, BDW22, 2N5875..76, ++
2N4906	Si-P	=2N4907: 60V	23a		BD312, BD546A, BDW22A, 2N5875..76, ++
2N4909	Si-P	=2N4907: 60V	23a		BD314, BD546B, BDW22B, 2N5876, ++
2N4910	Si-N	NF/S-L, 40V, 1A, 25W, >3MHz	22a	USA,Fch, Mot	BD239, BD241, BDY78, 2N4231..33, ++
2N4910	Si-N			Tho,Tix	—
2N4911	Si-N	=2N4910: 60V	22a		BD239A, BD241A, BDY78, 2N4232 .33, ++
2N4912	Si-N	=2N4910: 60V	22a		BD239B, BD241B, BDY78, 2N4233, ++
2N4913	Si-N	NF/S-L, 40V, 5A, 87,5W, >4MHz	22a	USA,Fch, Mot	BD245, BDV91, BDX91, 2N5873..74, ++
2N4913	Si-N			Rca,Tix	—
2N4914	Si-N	=2N4913: 60V	22a		BD245A, BDV91, BDX91, 2N5873..74, ++
2N4915	Si-N	=2N4913: 60V	22a		BD245B, BDV93, BDX93, 2N5874, ++
2N4916	Si-P	Uni, 30V, 0,1A, 0,2W, >400MHz, <55/180ns	8a	Fch,Nsc,Sgs	BSW24, BSX36, 2N2906. 07(A), 2N4125, ++
2N4917	Si-P	=2N4916: >450MHz	8a		BSW24, BSX36, 2N2906 07(A), 2N4125, ++
2N4918	Si-P	NF/S-L, 40V, 1A, 30W, >3MHz	14h	Mot,Nsc,Sgs	BD136, BD166, BD176, BD234, ++
2N4919	Si-P	=2N4918: 60V	14h		BD138, BD188, BD178, BD236, ++
2N4920	Si-P	=2N4918: 80V	14h		BD140, BD170, BD180, BD236, ++
2N4921	Si-N	NF/S-L, 40V, 1A, 30W, >3MHz	14h	Mot,Nsc,Sgs	BD135, BD165, BD175, BD233, ++
2N4922	Si-N	=2N4921: 60V	14h		BD137, BD167, BD177, BD235, ++
2N4923	Si-N	=2N4921: 80V	14h		BD139, BD189, BD179, BD237, ++
2N4924(S)	Si-N	Uni, 100V, 0,2A, 1W, >100MHz	2a	USA, Mot,Nsc	BC141, BC300, 2N1889..90, 2N1893, ++
2N4925(S)	Si-N	=2N4924: 150V	2a		BSS48..49, 2N3439..40, 2N5010
2N4926	Si-N	Vid, 200V, 0,05A, 1W, >30MHz	2a	USA, Mot,Sgs	BF258..259, BF658..659, 2N5058..59, ++
2N4927	Si-N	=2N4926: 250V	2a		BF258..259, BF658..659, 2N5058..59, ++
2N4928(S)	Si-P	Uni, 100V, 0,1A, 0,6W, >100MHz	2a	USA, Mot	BFT44..45, 2N3634..35, 2SB606
2N4929(S)	Si-P	Uni, 150V, 0,5A, 1W, >100MHz	2a	USA, Mot	BFT44..45, 2N3636..37, 2SB606
2N4930(S)	Si-P	Uni, 200V, 0,5A, 1W, >20MHz	2a	USA, Mot	BFT44..45, 2N5415..16, 2SB606
2N4931(S)	Si-P	Uni, 250V, 0,5A, 1W, >20MHz	2a	USA, Mot	BFT44..45, MJ5415..18, 2N5416, 2SB606
2N4932	Si-N	FM/VHF-L, 50V, 3,3A, PQ>12W(88MHz)	49a	Rca,Ssi,Tix	BLW36
2N4933	Si-N	FMA/HF-L, 70V, 3,3A, PQ>20W(88MHz)	49a	Rca,Ssi,Tix	2SC1037
2N4934	Si-N	VHF/UHF, 50V, 0,2W, >700MHz	5g	Mic,Nsc,Sca	BF377..378, BF689, BF763, 2N2857, ++
2N4935	Si-N	VHF/UHF, 50V, 0,2W, >700MHz	5g	Mic,Nsc,Sca	BF377 378, BF889, BF763, 2N2857, ++
2N4939	Si-N	VHF/UHF, 50V, 0,2W, >700MHz	5g	Mic,Nsc,Sca	BF377 378, BF889, BF763, 2N2857, ++
2N4937	Si-P	Dual, 50V, 0,05A, 0,6W, 400MHz	TO-77	Mot, Ray	2N3726 27, 2N4015 16
2N4938	Si-P	Dual, 50V, 0,05A, 0,6W, 400MHz	TO-77		2N3726..27, 2N4015..18
2N4939	Si-P	Dual, 50V, 0,05A, 0,6W, 400MHz	TO-77		2N3726..27, 2N4015. 16
2N4940	Si-P	=2N4937: 0,35W	10-FLP		—
2N4941	Si-P	=2N4938: 0,35W	10-FLP		—
2N4942	Si-P	=2N4938: 0,35W	10-FLP		—
2N4943	Si-N	NF/S, 120V, 1A, 0,8W, >150MHz	2a	USA, Mic,Nsc	B6S42 43, BSW67..68, BSX47, 2N2102++
2N4944	Si-N	Uni, 80/40V, 0,5A, 0,22W, >60MHz, B>40	8a	USA,Nsc,Sgs	BC639, BCX24, 2N3700..01, 2SD667, ++

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2N4945	Si-N	=2N4944: 80/60V	8a		BC639, BCX24, 2N3700..01, 2SD667, ++
2N4946	Si-N	=2N4944: B>100	8a		BC639, BCX24, 2N3700..01, 2SD667, ++
2N4947	UJT-P	Ip<2μA, Iv>2mA	2e	Mot, Tix	2N4851, 2N4948, 2N4893
2N4948	UJT-P	=2N4947	2e		2N4851, 2N4947, 2N4893
2N4949	UJT-P	=2N4947: Ip<1μA	2e		2N4894
2N495	Si-P	HF/S, 25V, 0,05A, 0,15W, >8MHz	2a	USA	BC213, BC258, BC308, BC558, ++
2N4950	Si-N	S-L, 80/60V, 70A, 200W	49m	USA	2N6309..11
2N4951	Si-N	Uni, 60V, 0,5A, 0,36W, 250MHz, B>60	7c	USA, Nsc, Tho	BC337A, BC637, BSV59, 2N2221..22(A)++
2N4952	Si-N	=2N4951: B>100	7c		BC337A, BC637, BSV59, 2N2221..22(A)++
2N4953	Si-N	=2N4951: B>200	7c		BC337A, BC637, BSV59, 2N2221..22(A)++
2N4954	Si-N	=2N4951: 40V	7c		BC337, BC635, BSV59, 2N2221..22(A)++
2N4955(/78)	Si-N	Dual, 30V, 0,03A, 0,45W, >60MHz	TO-77	Isi, Fch, Sca	2N3409..11
2N4955(/78)	Si-N			Sgs	—
2N4956(/78)	Si-N	Dual, 30V, 0,03A, 0,45W, >60MHz	TO-77		2N3409..11
2N4957	Si-P	UHF, ra, 30V, 0,03A, 0,2W, 1600MHz	5g	Mot, Sca, Tho	BF439, BF516, BF606, BFR38, BFR99++
2N4958	Si-P	UHF, ra, 30V, 0,03A, 0,2W, 1500MHz	5g	Mot, Sca, Tho	BF439, BF516, BF606, BFR39, BFR99++
2N4959	Si-P	UHF, ra, 30V, 0,03A, 0,2W, 1500MHz	5g	Mot, Sca, Tho	BF439, BF516, BF606, BFR38, BFR99++
2N496	Si-P	HF/S, 10V, 0,05A, 0,15W, >7,2MHz	2a	USA	BC213, BC258, BC308, BC558, ++
2N4960	Si-N	Uni, 60V, 1A, 0,8W, >250MHz	2a	Fch, Sca, Ssi	BC140..141, BSW65..68, BSX45..47, ++
2N4961	Si-N	=2N4960: 80V	2a		BC140..141, BSW65..68, BSX45..47, ++
2N4962	Si-N	=2N4960: 0,5W	2a		BC637, BSS40..41, BSX33, 2SD774, ++
2N4963	Si-N	=2N4960: 80V, 0,5W	2a		BC639, BSS58, BSX33, 2SD774, ++
2N4964	Si-P	Uni, 50V, 0,1A, 0,2W, >60MHz, B>30	8a	Fch, Mic, Nsc	BC212, BC257, BC307, BC557, ++
2N4965	Si-P	=2N4964: B>80	8a		BC212, BC257, BC307, BC557, ++
2N4966	Si-N	Uni, 50V, 0,03A, 0,2W, >40MHz, B>40	8a	Fch, Mic, Nsc	BC167, BC182, BC237, BC547, ++
2N4967	Si-N	=2N4966: B>100	8a		BC167, BC182, BC237, BC547, ++
2N4968	Si-N	=2N4966: 30V	8a		BC168, BC163, BC239, BC548, ++
2N4969	Si-N	Uni, 50V, 0,5A, 0,2W, >200MHz, B>40	8a	Fch, Mic, Nsc	BC337, BC637, BSV59, 2N2221..22(A), ++
2N497(A)	Si-N	Uni, 60V, 0,5A, 0,8..1W, 50MHz	2a	Fch, Tix, ++	BC140..141, BC300..302, 2N3053, ++
2N4970	Si-N	=2N4969: B>100	8a		BC337, BC637, BSV59, 2N2221..22(A), ++
2N4971	Si-P	Uni, 50V, 0,5A, 0,2W, >200MHz, B>40	8a	Fch, Mic, Nsc	BC327, BC638, BSW24, 2N2906..07(A), ++
2N4972	Si-P	=2N4971: B>100	8a		BC327, BC638, BSW24, 2N2906..07(A), ++
2N4973	Si-P	VHF/UHF, 20V, 0,03A, 0,2W, >800MHz	8a	Ray	BF316, BF4+F1418939, BF516, B606, BFR38++
2N4974	Si-P-Darl	Uni, 40V, 1A, 0,8W, β>25000	5	Mot, Ray	—
2N4975	Si-P-Darl	=2N4974: β>15000	5		—
2N4976	Si-N	UHF-L, 55V, 0,4A, 5W, >1GHz	55v	Trw	(BLW90, MRF5174)
2N4977	N-FET	S, Chopper, 30V, Idss>50mA, Up<10V	2b	USA, Tho, Tix	BFS74, BFS77, BSV78, 2N3970, 2N4391++
2N4978	N-FET	S, Chopper, 30V, Idss>15mA, Up<8V	2b	USA, Tho, Tix	BFS75, BFS78, BSV79, 2N4857, 2N4092++
2N4979	N-FET	S, Chopper, 30V, Idss>7,5mA, Up<5V	2b	USA, Tho, Tix	BFS76, BFS79, BSV80, 2N4858, 2N4093++
2N498(A)	Si-N	=2N497: 100V	2a	Fch, Tix, ++	BC141, BC300, 2N1689..90, 2N1990, ++
2N4980	Si-P	Chopper, 30/30/30V, 0,1A, 0,4W	2a	Tdy	2N2946
2N4981	Si-P	Chopper, 50/50/50V, 0,1A, 0,4W	2a	Tdy	—
2N4982	Si-P	Chopper, 70/70/70V, 0,1A, 0,4W	2a	Tdy	—
2N4983	SUS	Ub=6..10V, Is<0,5mA, Itsm=5A	2d(AKG)	Gen	—
2N4984	SUS	Ub=7,5..9V, Is<0,15mA, Itsm=5A	2d(AKG)	Gen	—
2N4985	SUS	Ub=7,5..8,2V, Is<0,3mA, Itsm=5A	2d(AKG)	Gen	—
2N4986	SUS	Ub=7..9V, Is<0,2mA, Itsm=5A	2d(AKG)	Gen	—
2N4987	SUS	=2N4983:	7a(KGA)	Gen	—
2N4988	SUS	=2N4984:	7a(KGA)	Gen	—
2N4989	SUS	=2N4985:	7a(KGA)	Gen	—
2N499(A)	Ge-P	VHF, 30V, 0,05A, >120MHz	2a	USA, Tix	AF106, AF109R, AF308
2N4990	SUS	=2N4986:	7a(KGA)	Gen	—
2N4991	SBS	Ub=6..10V, Is<0,5mA, Itsm=5A	7m(AGA)	Gen	—
2N4992	SBS	Ub=7,5..9V, Is<0,12mA, Itsm=5A	7m(AGA)	Gen	BS06A
2N4993	SBS	Ub=6..10V, Is<0,5mA, Itsm=5A	7m(AGA)	Gen	—
2N4994	Si-N	HF/ZF, 60V, 0,3A, 0,38W, 300MHz, B>40	7a	Gen, Mic, Tix	BF240..241, BF254..255, BF594..595, ++
2N4995	Si-N	=2N4994: B>100	7a		BF240..241, BF254..255, BF594..595, ++
2N4996	Si-N	VHF, 30V, 0,05A, 0,25W, >800MHz, B>50	7a	Mic, Sca, Tix	BF314, BF502, BF505, BF507, BF562++
2N4997	Si-N	=2N4996: B>30	7a		BF314, BF502, BF505, BF507, BF562++
2N4998	Si-N	S-L, 100V, 2A, 30W, >50MHz, B>30	49a	USA, Tix	2N5002, 2N5004, 2N5284..65
2N4999	Si-P	S-L, 100V, 2A, 30W, >50MHz, B>30	49a	USA, Tix	2N5003, 2N5005, 2N5288..87
2N50	Ge-P	S, 15V, 1mA, 0,05W		Civ	(ASY26..27, ASY48)
2N500	Ge-P	VHF, 20V, 0,05W	2a	Sem	AF109R, AF139, ÅF239(S)
2N5000	Si-N	=2N4998: >60MHz, B>70	49a		2N5002, 2N5004, 2N5284..85
2N5001	Si-P	=2N4999 >60MHz, B>70	49a		2N5003, 2N5005, 2N5286..87
2N5002	Si-N	S-L, 100V, 5A, 50W(Tc=50°), B>30	49a	USA, Tix	2N5284..85

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2N5003	Si-P	S-L, 100V, 5A, 50W(Tc=50°), B>30	49a	USA,Tix	2N5286..87
2N5004	Si-N	=2N5002: B>70	49a		2N5284..85
2N5005	Si-P	=2N5003: B>70	49a		2N5286..87
2N5006	Si-N	S-L, 100V, 10A, 87W(Tc=60°), B>30	49a	USA	2N5288..89
2N5007	Si-P	S-L, 100V, 10A, 67W(Tc=100°), B>30	49a	USA	2N5290..91
2N5008	Si-N	=2N5008: B>70	49a		2N5288..89
2N5009	Si-P	=2N5007: B>70	49a		2N5290..91
2N501(A,/18)	Ge-P	S, 15V, 0,05..0,2A, 0,06..0,15W, <-/22ns	2a	USA	ASZ21, 2N705(A), 2N2635, 2N2955..57
2N5010	Si-N	S, 500V, 0,5A, 4W(Tc=25°), 15MHz	2a	Sca,Ssi,Stc	BUY59..60, 2N3439, 2N5059, 2SD793..794+
2N5011	Si-N	=2N5010: 600V	2a		BUY60, 2N5097..99, 2SC1762, 2SD594
2N5012	Si-N	=2N5010: 700V	2a		2N5098..99, 2SC1762, 2SD594
2N5013	Si-N	=2N5010: 800V	2a		2N5099, 2SD594
2N5014	Si-N	=2N5010: 900V	2a		—
2N5015	Si-N	=2N5010: 1000V	2a		—
2N5016	Si-N	UHF-L, 65V, 4,5A, PQ>15W(400MHz)	49a	Mot,Rca,Sem	—
2N5016	Si-N			Ssi,Tho,Tix	—
2N5017	Si-N	UHF-L, 65V, 4,5A, PQ>15W(400MHz)		Rca	—
2N5018	P-FET	Uni, 30V, Idss>10mA, Up<10V	2a	USA,Nsc,Tix	2N3993
2N5019	P-FET	Uni, 30V, Idss>5mA, Up<5V	2a	USA,Nsc,Tix	2N5118
2N502(A,B)	Ge-P	VHF, 20..30V, 0,05A, 220MHz	2a	USA, Mot	AF108, AF109R, AF306
2N5020	P-FET	Uni, 25V, Idss>0,3mA, Up<1,5V	2a	USA,Fch,Nsc	2N2844
2N5021	P-FET	Uni, 25V, Idss>1mA, Up<2,5V	2a	USA,Fch,Nsc	2SJ74
2N5022	Si-P	S, 50V, 0,5A, 1W, <45/95ns	2a	USA,Fch,Mic	2N3488, 2SA717, 2SA742
2N5022	Si-N			Mot,Nsc	—
2N5023	Si-P	S, 30V, 0,5A, 1W, <45/95ns	2a	=2N5022	2N3467..68, 2SA717, 2SA742
2N5024	Si-N	UHF, 20V, 15mA, 0,2W, >1300MHz	5g	Sca	BF377..378, BF630, BFR15, BFW99, ++
2N5025	Si-N	HF-L, 75V, 5A, PQ>20W(50MHz)	49a	Fch,Tix	—
2N5026	Si-N	HF-L, 90V, 5A, PQ>25W(50MHz)	49a	Fch,Tix	—
2N5027	Si-N	S, -/30V, 0,35A, 0,32W, <35/60ns	7c	Gen,Nsc	BSS10..11, BSX19..20, 2N2368..69(A), ++
2N5029	Si-N	S, -/30V, 0,35A, 0,32W, <45/70ns	7c	Gen,Nsc	BSS10..11, BSX19..20, 2N2368..69(A), ++
2N5029	Si-N	S, -/15V, 0,2A, 0,32W, <22/26ns	7c	Gen,Mic,Nsc	BSS10..11, BSX19..20, 2N2368..69(A), ++
2N503	Ge-P	VHF, 20V, 0,05A, 0,025W, >168MHz	2a	USA	AF109R, AF139, AF239(S)
2N5030	Si-N	S, -/12V, 0,2A, 0,32W, <24/30ns	7c	Gen,Mic,Nsc	BSS10..11, BSX19..20, 2N2368..69(A), ++
2N5031	Si-N	UHF, ra, 15V, 0,02A, 0,2W, >1GHz	5g	USA, Mot	BF377..378, BF689, BF763, 2N2857, ++
2N5032	Si-N	UHF, ra, 15V, 0,02A, 0,2W, >1GHz	5g	USA, Mot	BF377..378, BF689, BF763, 2N2857, ++
2N5033	P-FET	Uni, 20V, Idss>0,3mA, Up<2,5V	8b	USA,Fch,Nsc	2N2607
2N5034	Si-N	NF/S-L, 55V, 6A, 83W, >0,8MHz		Rca	BD245, BD545A, BDV91, 2SC3256, ++
2N5035	Si-N	NF/S-L, 55V, 6A, 83W, >0,8MHz		Rca	BD245, BD545A, BDV91, 2SC3256, ++
2N5036	Si-N	=2N5034: 70V, 6A		Rca	BD245A, BD545B, BDV93, 2SC3256, ++
2N5037	Si-N	=2N5035: 70V, 8A		Rca	BD245A, BD545B, BDV93, 2SC3256, ++
2N5038(-1)	Si-N	S-L, 150V, 20A, 140W, >60MHz	23a	USA,EUR,Tos	BUV10, BUW57, BUX10, BUX40
2N5039(-1)	Si-N	=2N5038: 120V	23a		BUV10, BUW57, BUX10, BUX40
2N504	Ge-P	HF, 35V, 0,05A, 0,03W, >50MHz	2a	USA	AF124..128, AF200
2N5040	Si-P	Uni, 25V, 1A, 0,3W, >80MHz	2a	Fch	BC160..161, BC327..328, BC636, ++
2N5041	Si-P	Uni, 40V, 1A, 0,3W, >100MHz	2a	Fch	BC160..161, BC327..328, BC636, ++
2N5042	Si-P	Uni, 40V, 1A, 0,8W, >100MHz	2a	Fch	BC160..161, BCX60, 2N2904..05(A), ++
2N5043	Ge-P	VHF/UHF, ra, 15V, 0,03A, >1500MHz	5g	Ssi,Tix	(AF239(S))
2N5044	Ge-P	VHF/UHF, ra, 15V, 0,03A, >1000MHz	5g	Ssi,Tix	(AF239(S))
2N5045	N-FET	Dual, 50V, Idss>0,5mA, Up<4,5V	TO-71	USA,Nsc,Tix	BFQ10..18, 2N3921..22, 2N3954..58
2N5046	N-FET	Dual, 50V, Idss>0,5mA, Up<4,5V	TO-71		BFQ10..16, 2N3921..22, 2N3954..58
2N5047	N-FET	Dual, 50V, Idss>0,5mA, Up<4,5V	TO-71		BFQ10..18, 2N3921..22, 2N3954..58
2N5048	Si-N	S-L, 120V, 10A, 50W(Tc=100°), >10MHz	49m	USA	2N5288..89, 2N5542
2N5049	Si-N	=2N5048: 60V	49m	USA	2N5288..89, 2N5542
2N505	Ge-P	NF, 40V, 0,25A, 0,125W, 8MHz	2a	Csr,Etc	(ASY46, ASY76..77)
2N5050	Si-N	NF/S-L, 125V, 2A, 40W, >10MHz	22a	USA,Mot,Rca	BD241D, BUX67(A..C), 2N3441, 2SD1138++
2N5051	Si-N	=2N5050: 150V	22a		BD241D, BUX67(A..C), 2N3441, 2SD1136++
2N5052	Si-N	=2N5050: 200V	22a		BD241F, BUX87(A..C), 2N3563, 2SD1138++
2N5053	Si-N	UHF, 30V, 0,025A, 0,2W, >1300MHz	5g	Amp,Sca,Ssi	BF377..378, BF830, BFR15, BFW99, ++
2N5054	Si-N	UHF, 30V, 0,025A, 0,2W, >1500MHz	5g	Amp,Sca,Ssi	BF377..378, BF630, BFR15, BFW99, ++
2N5055	Si-P	S, 12V, 0,1A, 0,2W, <25/36ns	8a	Fch,Nsc	BSX36, 2N4313
2N5056	Si-P	S, 15V, 0,1A, 0,36W, <25/45ns	2a	Fch,Itt,Nsc	BSX38, 2N4313
2N5057	Si-P	S, 15V, 0,1A, 0,36W, <25/45ns	2a	Fch,Itt,Nsc	BSX38, 2N4313
2N5058(S)	Si-N	S/Vid, 300V, 0,15A, 1W, >30MHz	2a	USA,Mot,Tix	BF259, BF659, BFS89, BFR59
2N5059(S)	Si-N	=2N5056: 250V	2a		BF288..259, BF658..659, BFS89, ++
2N506	Ge-P	NF/S, 40V, 0,1A, 0,05W	2a	Csr,Etc	2N1191..94, 2SB56A
2N5060	50Hz-Thy	30V, 0,51A(Tc=67°), Igt/Ih<0,2/<5mA	7n	Gen,Mot,Tag	2N6564, TIC60, MCR100-3, BRY55/30, ++

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2N5060	50Hz-Thy			Phi,Tix,Uni	—
2N5061	50Hz-Thy	=2N5060: 50V	7n		2N6564, TIC61, MCR100-3, BRY55/60, ++
2N5062	50Hz-Thy	=2N5060: 100V	7n		2N6564, TIC62, MCR100-3, BRY55/100, ++
2N5063	50Hz-Thy	=2N5060: 150V	7n		2N6564, TIC63, MCR100-4, BRY55/200, ++
2N5064	50Hz-Thy	=2N5060: 200V	7n		2N6564, TIC64, MCR100-4, BRY55/200, ++
2N5065	Si-N	S, RadH, 25V, 0,5A, 0,6W, <19/40ns	2a	Fch,Sca,Sgs	—
2N5066	Si-N	Chopper, 30/20/30V, 0,1A, 0,4W	2a	Tdy	—
2N5067	Si-N	NF/S-L, 40V, 5A, 87,5W, >4MHz	23a	USA,Mot,Tix	BD245, BDV91, BDX91, 2N4914..15, ++
2N5068	Si-N	=2N5067: 60V	23a		BD245A, BDV91, BDX91, 2N4914..15, ++
2N5069	Si-N	=2N5067: 80V	23a		BD245B, BDV93, BDX93, 2N5758..60, ++
2N507	Ge-N	NF/S, 40V, 0,1A, 0,05W	2a	Csr,Etc	—
2N5070	Si-N	AM-L, 65V, 3,3A, PEP=25W(30MHz)	49a	Mot,Rca,Sam	2N5026
2N5070	Si-N			Tix,Tho	—
2N5071	Si-N	FM-L, 65V, 3,3A, PQ>24W(76MHz)	49a		2N5026
2N5072	Si-N	S-L, 100V, 10A, 125W, >40MHz		Ssi,Tho,Trw	—
2N5073	Si-N	Vid, 160V, 0,4A, 0,6W, >40MHz	2a	Sca,Ssi,Tho	BFW36, BSS48, 2SD413, 2SD576, 2SD624
2N5074	Si-N	S-L, 200/200V, 3A, 40W(Tc=100°), B>30	49a	USA	—
2N5075	Si-N	=2N5074: B>90	49a		—
2N5076	Si-N	=2N5074: 250/250V	49a		—
2N5077	Si-N	=2N5074: 250/250V, B>90	49a		—
2N5078	N-FET	VHF/UHF, ra, 30V, Idss>4mA, Up<6V	5n	USA,Isi,Nsc	BF244B..245B, BFS72, 2N3823, 2N5398
2N5079	Si-N	Uni, 60V, 1A, 0,36W, >400MHz	2a	Csr,Idi,Tdy	BFX94..95, 2N3737, 2N4014
2N506	Ge-P	NF-Tr, 16V, 0,5A, 0,225W	2a(B=case)	USA,Mot	AC128, AC152..153, AC166
2N5080	Si-N	Uni, 60V, 1A, 0,36W, >500MHz	2a		BFX94..95, 2N3737, 2N4014
2N5081	Si-N	HF, 70V, 0,36W, >600MHz	2a	Csr,Idi,Tdy	—
2N5082	Si-N	HF, 60V, 0,36W, >600MHz	2a		—
2N5083	Si-N	S-L, 120V, 10A, 25W(Tc=100°), B>40	49a	USA	(2N5266..89, 2N5542)
2N5084	Si-N	=2N5083: B>100	49a		(2N5266..89, 2N5542)
2N5085	Si-N	=2N5083: 150V	49a		(2N5542)
2N5086	Si-P	NF, ra, 50V, 0,05A, 0,625W, B>150	7e	USA,Fer,Mot	BC214, BC416, BC550, 2SA872(A), ++
2N5086	Si-P			Phi,Tix,++	—
2N5087	Si-P	=2N5086: B>250	7a		BC214, BC416, BC560, 2SA872(A), ++
2N5088	Si-N	NF, ra, 35V, 0,05A, 0,625W, B>300	7a	USA,Mic,Mot	BC169, BC164, BC239, BC549, ++
2N5088	Si-N			Nsc,Phi	—
2N5089	Si-N	=2N5088: 30V, B>400	7a		BC189, BC164, BC239, BC549, ++
2N508A	Ge-P	=2N508: 30V, 0,2A, 0,2W	2a(B=case)		AC126, AC152..153, AC166
2N509	Ge-P	UHF, 30V, 0,04A, 750MHz	2a	Wes	AF139, AF239(S)
2N5090	Si-N	VHF/UHF-Tr/E, 55V, 0,4A, PQ>1,2W(400MHz)	49a	Mot,Rca,Sca	—
2N5090	Si-N			Sam,Tho,Tix	—
2N5091	Si-P	NF/S, 350/300V, 1A, 4W(Tc=25°)	2a	Sca,Ssi,Stc	MJ5416, 2N5416
2N5092	Si-N	NF/S, 400/350V, 1A, 4W(Tc=25°)	2a	Sca,Ssi,Stc	BSS49, BUX55, BUY59..60, 2N3439
2N5093	Si-P	NF/S, 400/350V, 1A, 4W(Tc=25°)	2a	Sca,Ssi,Stc	MJ5416
2N5094	Si-P	NF/S, 450/400V, 1A, 4W(Tc=25°)	2a	Sca,Ssi,Stc	MJ5416
2N5095	Si-N	NF/S, 500/400V, 1A, 4W(Tc=25°)	2a	Sca,Ssi,Stc	BUX55, BUY59..60, 2N3439
2N5096	Si-P	NF/S, 500/450V, 1A, 4W(Tc=25°)	2a	Sca,Ssi,Stc	MJ5416
2N5097	Si-N	NF/S, 600/450V, 1A, 4W(Tc=25°)	2a	Sca,Ssi,Stc	BUY60
2N5098	Si-N	NF/S, 700/500V, 1A, 4W(Tc=25°)	2a	Sca,Ssi,Stc	—
2N5099	Si-N	NF/S, 600/550V, 1A, 4W(Tc=25°)	2a	Sca,Ssi,Stc	—
2N51	Ge-P	S, 50V, 6mA, 0,1W		Civ	(ASY48)
2N5100	Si-P	S-L, 450/400V, 1A, 10W, >20MHz	43m	Sca,Ssi,Stc	—
2N5101	Si-N	S-L, 500/400V, 1A, 10W, >50MHz	43m	Sca,Ssi,Stc	(BD410, BUV83, BUV93..95, BUW40A,B)
2N5102	Si-N	VHF-L, 100V, 3,3A, PQ=15W(136MHz)	49a	Rca,Sam,Tix	BLY36, 2N3632
2N5103	N-FET	Uni, 25V, Idss>1mA, Up<4V	5k	Isi,Nsc,++	2N5246, 2N5360, 2SK161
2N5104	N-FET	Uni, 25V, Idss>2mA, Up<4V	5k	Isi,Nsc,++	2N5246, 2N5360, 2SK107
2N5105	N-FET	Uni, 25V, Idss>5mA, Up<4V	5k	Isi,Nsc,++	BF256, BFS60, BFW11, 2N5465, ++
2N5106	Si-N	S, RadH, 60V, 0,6A, 0,8W, >250MHz	2a		—
2N5107	Si-N	=2N5106: 0,36W, RadH	2a		—
2N5108(A)	Si-N	UHF-O/Tr, 55V, 0,4A, PQ>1W(1GHz)	2a		—
2N5109	Si-N	VHF/UHF-A, 40V, 0,4A, >1200MHz	2a		BFS50, MRF515, MRF629, 2N3948, ++
2N511	Ge-P	NF/S-L, 40V, 25A, 150W	23a	USA,Tix	2N1651..53, 2N2285..67
2N5110	Si-P	NF/S, 40V, 1A, 0,5W, >1MHz	2a		BC160..161, BCX60, BSV15..17, ++
2N5111	Si-P	=2N5110: 60V	2a		BC161, BCX60, BSS18, BSV16..17, ++
2N5112	Si-P	=2N5110: 34W	49a		—
2N5113	Si-P	=2N5110: 60V, 34W	49a		—
2N5114	P-FET	S, 30V, Idss>30mA, Up<10V, 16/21ns	2a	USA,Nsc,Phi	—
2N5115	P-FET	S, 30V, Idss>15mA, Up<6V, 30/36ns	2a	USA,Nsc,Phi	—

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2N5116	P-FET	S,30V,Idss>5mA,Up<4V,42/60ns	2a	USA,Nsc,Phi	—
2N5117	Si-P	Dual,ra,45V,10mA,0,75W,>100MHz	TO-77	Isi,Sol	BFX11,2N3726,2N40415..16
2N5118	Si-P	Dual,ra,45V,10mA,0,75W,>100MHz	TO-77		BFX11,2N3726,2N40415..16
2N5119	Si-P	Dual,ra,45V,10mA,0,75W,>100MHz	TO-77		BFX11,2N3726,2N40415..16
2N511A	Ge-P	=2N511:60V	23a		2N1651..53,2N2285..87
2N511B	Ge-P	=2N511:60V	23a		2N1652..53,2N2286..87
2N512	Ge-P	NF/S-L,40V,25A,150W	23a	USA,Tix	2N1651..53,2N2285..87
2N5120	Si-P	=2N5117:0,5W	TO-71		(BFX11,2N3726,2N40415..16)
2N5121	Si-P	=2N5118:0,5W	TO-71		(BFX11,2N3726,2N40415..16)
2N5122	Si-P	=2N5119:0,5W	TO-71		(BFX11,2N3726,2N40415..16+F14276)
2N5123	Si-P	=2N5117:0,75W			—
2N5124	Si-P	=2N5117:0,75W			—
2N5125	Si-P	=2N5117:0,75W			—
2N5126	Si-N	HF/ZF,re,20V,0,03A,0,2W,>300MHz	6a	Fch,Sem,Tdy	BF240..241,BF254..255,BF594..595,++
2N5127	Si-N	HF/ZF,20V,0,1A,0,2W,>150MHz	6a	USA,Mic,Nsc	BF240..241,BF254..255,BF594..595,++
2N5128	Si-N	Uni,15V,0,5A,0,3W,>200MHz	8a	USA,Mic,Nsc	BC337..338,BC635,2N2221..22(A),++
2N5129	Si-N	=2N5126:0,2W	8a		BC337..338,BC635,2N2221..22(A),++
2N512A	Ge-P	=2N512:60V	23a		2N1651..53,2N2285..87
2N512B	Ge-P	=2N512:60V	23a		2N1652..53,2N2286..87
2N513	Ge-P	NF/S-L,40V,25A,150W	23a	USA,Tix	2N1651..53,2N2265..67
2N5130	Si-N	HF,30V,0,05A,0,2W,>450MHz	8a	USA,Mic,Nsc	BF314,BF502,BF505,BF507,BF562++
2N5131	Si-N	Uni,20V,0,2A,0,2W,>100MHz	8a	USA,Nsc	BC166,BC183,BC238,BC548,++
2N5132	Si-N	HF,20V,0,05A,0,2W,>200MHz	8a	USA,Mic,Nsc	BF240..241,BF254..255,BF594..595,++
2N5133	Si-N	Uni,20V,0,05A,0,2W,>40MHz	8a	USA,Mic,Nsc	BC168,BC183,BC238,BC546,++
2N5134	Si-N	S,20V,0,1A,0,2W,<26/26ns	6a	USA,Mic,Nsc	BSS11..12,BSV89..92,2N2368..69(A),++
2N5135	Si-N	Uni,30V,0,2A,0,3W,>40MHz	8a	USA,Mic,Nsc	BC168,BC183,BC238,BC548,++
2N5136	Si-N	Uni,30V,0,5A,0,3W,>40MHz	8a	USA,Mic,Nsc	BC337..338,BC635,BC637,BC639,++
2N5137	Si-N	=2N5136:0,22W	8a		BC337..338,BC635,BC637,BC639,++
2N5138	Si-P	Uni,50V,0,05A,0,2W,>30MHz	8a	USA,Mic,Nsc	BC212,BC257,BC307,BC557,++
2N5139	Si-P	S,20V,0,1A,0,2W,<65/230ns	8a	USA,Mic,Nsc	BSW24,2N3209,2N4034..35,2N4125..26++
2N513A	Ge-P	=2N513:60V	23a		2N1651..53,2N2285..87
2N513B	Ge-P	=2N513:60V	23a		2N1652..53,2N2286..87
2N514	Ge-P	NF/S-L,40V,25A,150W	23a	USA,Tix	2N1651..53,2N2285..87
2N5140	Si-P	S,5V,0,05A,0,2W,<35/35ns	8a	USA,Mic,Nsc	BSX36,2N4258,2N4313,2N5056..57
2N5141	Si-P	S,6V,0,1A,0,2W,<115/170ns	8a	USA,Mic,Nsc	BSW24,2N3209,2N4034..35,2N4125..26++
2N5142	Si-P	Uni,20V,0,5A,0,3W,<120/225ns	8a	USA,Mic,Nsc	BC327..328,BC636,2N2906..07(A),++
2N5143	Si-P	=2N5142:0,2W	8a		BC327..328,BC636,2N2906..07(A),++
2N5144	Si-N	S,RadH,50V,0,5A,0,36W,<45/65ns	2a	Fch	—
2N5145	Si-N	=2N5144:0,8W,RadH	2a	Fch	—
2N5146	Si-P	4xPNP,40V,1,5A,0,6W,250MHz	14-FLP	Fch,Mot	—
2N5147	Si-P	=2N4999:1W	2a	USA,Nsc,Tix	BSS17,2N5322
2N5148	Si-N	=2N4998:1W	2a	USA,Nsc,Tix	BSS15,2N5320
2N5149	Si-P	=2N5001:1W	2a	USA,Nsc,Tix	BSS17,2N5322
2N514A	Ge-P	=2N514:60V	23a		2N1651..53,2N2285..87
2N514B	Ge-P	=2N514:60V	23a		2N1652..53,2N2286..87
2N515	Ge-N	NF/HF,18V,0,25A,0,05W,3MHz	2a	Csr,Etc	(ASY28..29)
2N5150	Si-N	=2N5000:1W	2a	USA,Nsc,Tix	BSS15,2N5320
2N5151	Si-P	=2N5003:1W	2a	USA,Sgs,Tix	BUY90,2N6192..93
2N5152	Si-N	=2N5002:1W	2a	USA,Sgs,Tix	BUX34,BUY80,2N5338..39
2N5153	Si-P	=2N5005:1W	2a	USA,Sgs,Tix	BUY90,2N6192..93
2N5154	Si-N	=2N5004:1W	2a	USA,Sgs,Tix	BUX34,BUY80,2N5338..39
2N5155	Ge-P	S-L,140V,15A,106W	23a	USA,Del,Mot	—
2N5156	Ge-P	S-L,100V,10A,93W	23a	USA,Del,Mot	AL100..101,AUY37,2N2290,2N2293,++
2N5157	Si-N	S-L,700/400V,3,5A,100W(Tc=75°)	23a	USA,Mot,Tix	BUS11(A),BUX46(A),2SC3091,2SC3155++
2N5158	N-FET	S,Chopper,40V,Idss<100mA,Up<8V	2a	Tdy	BFS74,BFS77,BSV78,2N3970,++
2N5159	N-FET	S,Chopper,40V,Idss<100mA,Up<10V	2a	Tdy	BFS74,BFS77,BSV78,2N3970,++
2N516	Ge-N	NF/HF,18V,0,25A,0,05W,3MHz	2a	Csr,Etc	(ASY28..29)
2N5160	Si-P	VHF/UHF-Tr/E,60V,0,4A,PQ=1,2W(400MHz)	2a	Mot,Ray	—
2N5161	Si-P	VHF-L,60V,1,5A,PQ=8,5W(175MHz)	49a	Mot,Ray	—
2N5162	Si-P	VHF-L,60V,5A,PQ=35W(175MHz)	49a	Mot,Ray	—
2N5163	N-FET	VHF,25V,Idss>1mA,Up<8V	6b	USA,Mic,Nsc	BF244..245,BFS72,BFW10,2N3823
2N5164	50Hz-Thy	50V,13A(Tc=67°),Igt/Ih<40/<50mA	29b	Gen,Mot	MCR3818-2,2N3870,MCR3835-2,MCR63-2
2N5164..5167R	50Hz-Thy	=2N5164..5167:	29d		→2N5164..5167
2N5165	50Hz-Thy	=2N5164:200V	29b		MCR3818-4,2N3871,MCR3835-4,MCR63-4
2N5166	50Hz-Thy	=2N5164:400V	29b		MCR3816-6,2N3872,MCR3835-6,MCR63-6
2N5167	50Hz-Thy	=2N5164:600V	29b		MCR3818-8,2N3873,MCR3835-8,MCR63-8

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2N5168	50Hz-Thy	=2N5164:	21b		MCR3918-2, T12N100, MCR3935-2, MCR64-2
2N5168...5171R	50Hz-Thy	=2N5168..5171:	21d		→2N5168..5171
2N5169	50Hz-Thy	=2N5165:	21b		MCR3918-4, T12N200, MCR3935-4, MCR64-4
2N517	Ge-N	NF/HF, 18V, 0,25A, 0,05W, 3MHz	2a	Csr,Etc	(ASY28..29)
2N5170	50Hz-Thy	=2N5165:	21b		MCR3918-6, T12N400, MCR3935-6, MCR64-6
2N5171	50Hz-Thy	=2N5168:	21b		MCR3918-8, T12N600, MCR3935-8, MCR64-8
2N5172	Si-N	Uni, 25V, 0,1A, 0,36W, 200MHz	7c	USA,Mic,Nsc	BC168, BC188, BC238, BC548, ++
2N5174	Si-N	Uni, 90V, 0,025A, 0,38W	7c	Gen,Spr	BSS38, BSX21, 2SC1890(A), 2SC2240, ++
2N5175	Si-N	Uni, 130V, 0,025A, 0,2W	7c	Gen,Spr	BSS38, BSX21, 2SC1890A, 2SC2240, ++
2N5176	Si-N	Uni, 130V, 0,025A, 0,38W	7c		BSS38, BSX21, 2SC1890A, 2SC2240, ++
2N5177	Si-N	HF-L, 55V, 4A, 40W, >200MHz	60c	Trw	—
2N5178	Si-N	HF-L, 55V, 8A, 70W, >200MHz	80c	Trw	—
2N5179	Si-N	VHF/UHF, ra, 20V, 0,05A, 0,2W, 1400MHz	5g	USA,Mot,Nsc	BF377..378, BF689, BF783, 2N2857, ++
2N5179	Si-P			Rca,Sgs,Tix	—
2N518	Ge-P	NF/S, 45V, 0,125A, 0,15W, 11MHz	1a	Csr,Etc	(ASY48, ASY76..77)
2N5180	Si-N	VHF, ra, 30V, 0,18W, 900MHz	5g	USA,Rca,Tix	BF314, BF502, BF505, BF507, BF562++
2N5181	Si-N	HF/ZF, 45V, 0,05A, 0,18W, 700MHz	5k	USA,Nsc,Rca	BF198..199, BF224..225, BF310..311, ++
2N5182	Si-N	HF/ZF, 45V, 4mA, 0,18W, 700MHz	5k	USA,Nsc,Rca	BF198..199, BF224..225, BF310..311, ++
2N5183	Si-N	Uni, 18V, 1A, 0,5W, <75/575ns	2a	USA,Rca	BC337..338, BC635, 2N2221..22(A), ++
2N5184	Si-N	Vid, -/120V, 0,05A, 0,5W, 100MHz	2a	Rca,Sem	BF297..299, BFT57..59, 2SC3467, ++
2N5185	Si-N	=2N5184: 1W	2a*		BF297..299, BFT57..59, 2SC3467, ++
2N5168	Si-N	S, 10V, 0,3A, 0,3W, 600MHz, <25/25ns	2a	Rca,Sem	BSS10..12, BSX19..20, 2N3261, ++
2N5187	Si-N	SS, 25V, 0,5A, 0,3W, 600MHz, <12/14ns	2a	Rca,Sca,Sem	BSS10, BSX28, BSX39, 2N3281
2N5168	Si-N	S, 60V, 1A, 0,8W, 325MHz, <35/50ns	2a	USA,Rca	BSS27, BSV77, BSV95, 2SC1635, ++
2N5169	Si-N	S, 60V, 1A, 1W, >250MHz, <40/70ns	2a	USA,Rca,Tix	BSS27, BSV77, BSV95, 2SC1635, ++
2N519(A)	Ge-P	NF/S, 15..25V, 0,1..0,15W, >0,5MHz	2a	USA	ASY28..27, ASY76..77
2N5190	Si-N	NF/S-L, 40V, 4A, 40W, >2MHz	14h	Mot,Nsc,Sgs	BD165, BD437, BD785, MJE240..244, ++
2N5191	Si-N	=2N5190: 60V	14h		BD187, BD439, BD787, MJE240..244, ++
2N5192	Si-N	=2N5190: 80V	14h		BD189, BD441, BD789, MJE240..244, ++
2N5193	Si-P	NF/S-L, 40V, 4A, 40W, >2MHz	14h	Mot,Nsc,Sgs	BD168, BD438, BD786, MJE250..254, ++
2N5194	Si-P	=2N5193: 60V	14h		BD188, BD440, BD768, MJE250..254, ++
2N5195	Si-P	=2N5193: 60V	14h		BD190, BD442, BD788, MJE250..254, ++
2N5198	N-FET	Dual, ra, 50V, Idss>0,7mA, Up<4V	TO-71	Isi,Nsc,Six	—
2N5198	N-FET			Tho,Tix,++	—
2N5197	N-FET	Dual, ra, 50V, Idss>0,7mA, Up<4V	TO-71		—
2N5198	N-FET	Dual, ra, 50V, Idss>0,7mA, Up<4V	TO-71		—
2N5199	N-FET	Dual, ra, 50V, Idss>0,7mA, Up<4V	TO-71		—
2N52	Ge-P	S, 50V, 8mA, 0,12W		Clv	(ASY48)
2N520(A)	Ge-P	NF/S, 15..25V, 0,1..0,15W, >3MHz	2a	USA	ASY28..27, ASY78..77
2N5200	Si-N	UHF, RadH, 20V, 0,1A, 0,3W, >900MHz	2a	Fch,Sca	—
2N5201	Si-N	UHF, RadH, 20V, 0,1A, 0,3W, >1100MHz	2a		—
2N5202	Si-N	NF/S-L, 100V, 4A, 35W, >60MHz	22a	USA,Rca	BDV10..12, 2SD772
2N5203	Si-N	=BFW35	2a		→BFW35
2N5204	50Hz-Thy	600V, 22A(Tc=40°), Igt/Ih<40/<100mA	21b	USA,Tho,Tag	C228M, 2N3899, MCR3935-8, C35M, ++
2N5205	50Hz-Thy	=2N5204: 800V	21b		MCR3935-10, C35N, MCR64-10, TAG35-800
2N5206	50Hz-Thy	=2N5204: 1000V	21b		C35P, MCR64-10, TAG35-1000
2N5207	50Hz-Thy	=2N5204: 1200V	21b		—
2N5206	Si-P	FM/V+C14340HF, ra, 30V, 0,05A, 0,35W, >300MHz	7f	Mot	BF324, BF414, BF506, BF914, BF936++
2N5209	Si-N	NF, ra, 50V, 0,05A, 0,625W, 90MHz	7e	USA,Fer,Mot	BC184, BC413..414, BC550, 2SC2240, ++
2N5209	Si-N			Mic,Nsc,Tix	—
2N521(A)	Ge-P	NF/S, 15..25V, 0,1..0,15W, >8MHz	2a	USA	ASY28..27
2N5210	Si-N	NF, ra, 50V, 0,05A, 0,625W, 80MHz	7e		BC184, BC413..414, BC550, 2SC2240, ++
2N5211	Si-N	VHF-Tr, 60V, 0,6A, 0,8W, >200MHz	2a	Itt	BFS23, BLY34
2N5212	Si-N	VHF-Tr/E, 60V, 0,6A, 7,5W, >200MHz	43a	Itt	—
2N5213	Si-N	VHF/UHF-Tr/E, 70V, 0,5A, PQ=3W(200MHz)	43a	Itt	--
2N5214	Si-N	VHF-L, 95V, 5A, PQ=30W(150MHz)		Itt	(BLY94, 2SC2182)
2N5215	Si-N	VHF-L, 70V, 1A, PQ=10W(200MHz)	49a	Itt,Tix	BLY60, 2N3832
2N5218	Si-N	VHF/UHF-L, 80V, 1,5A, PQ=15W(400MHz)		Itt	(BLW94, BLX94, MRF323, 2SC1118)
2N5217	Si-N	VHF/UHF-Tr/E, 60V, 0,5A, PQ=4W(400MHz)		Itt	(BLW94, BLX94, MRF323, 2SC1118)
2N5218	Si-N	S-L, 220/200V, 10A, 50W(Tc=100°)	49m	USA	2N5540
2N5219	Si-N	Uni, 20V, 0,1A, 0,35W, >150MHz	7e	USA,Mot,Tix	BC168, BC183, BC238, BC548, ++
2N522(A)	Ge-P	NF/S, 15..25V, 0,1..0,15W, >15MHz	2a	USA	ASY28..27
2N5220	Si-N	Uni, 15V, 0,5A, 0,625W, >100MHz	7e	USA,Mot,Tix	BC337..338, BC635, BC637, BC639, ++
2N5221	Si-P	Uni, 15V, 0,5A, 0,35W, >100MHz	7e	USA,Mot,Tix	BC327..328, BC636, BC638, BC640, ++
2N5222	Si-N	AM/FM, TV-ZF, 20V, 0,05A, >450MHz	7f	USA,Mot,Tix	BF198..199, BF224..225, BF310..311, ++
2N5223	Si-N	Uni, 25V, 0,1A, 0,625W, >150MHz	7e	USA,Mot,Tix	BC168, BC163, BC238, BC548, ++

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2N5224	Si-N	NF/S, 25V, 0,2A, 0,625W, <45/60ns	7e	USA, Mot	BSS 10..12, BSX 19..20, 2N2368..69(A),++
2N5225	Si-N	Uni, 25V, 0,5A, 0,625W, >50MHz	7e	USA,Mot,Tix	BC 337..338, BC635, BC637, BC639, ++
2N5226	Si-P	Uni, 25V, 0,5A, 0,625W, >50MHz	7e	USA,Mot,Tix	BC 327..326, BC636, BC638, BC640, ++
2N5227	Si-P	Uni, 30V, 0,05A, 0,625W, >100MHz	7e	USA,Mot,Tix	BC 213, BC 258, BC 306, BC 558, ++
2N5226	Si-P	NF/S, 5V, 0,05A, 0,625W, <75/140ns	7e	USA, Mot	BSW24, BSX38, 2N4256, 2N4313, ++
2N5229	Si-P	Chopper, 15/10/15V, 0,05A, 0,5W	2a	Mot,Ssi	2N2944
2N523(A)	Ge-P	NF/S, 15..20V, 0,1..0,15W, >21MHz	2a	USA	(ASY 26..27)
2N5230	Si-P	Chopper, 30/20/30V, 0,05A, 0,5W	2a	Mot,Ssi	2N2945
2N5231	Si-P	Chopper, 50/30/50V, 0,05A, 0,5W	2e	Mot,Ssi	2N2946
2N5232(A)	Si-N	Uni, ra, 70V, 0,1A, 0,36W, >250MHz	7c,7e	USA,Mic,Nsc	2SC1775(A), 2SC2240, 2SC2389, 2SC2459,++
2N5233	Si-N	Uni, 80V, 0,1A, 0,33W, B>100	7c	Csr	BC 546, 2SC1890(A), 2SD755..756(A), ++
2N5234	Si-N	=2N5233: B>250	7c		BC 546, 2SC1890(A), 2SD755..756(A), ++
2N5235	Si-N	=2N5233: B>400	7c		BC546, 2SC1890(A), 2SD755..756(A), ++
2N5238	Si-N	HF-O, ZF, 40V, 0,15A, 0,6W, >500MHz, RadH	2a	Fch,Sca,Ssi	—
2N5237	Si-N	S, 150V, 5A, 6,75W(Tc=25°), 25MHz	2a	USA	BUY 80, 2N4879
2N5238	Si-N	=2N5237: 200V	2a		BUY 48..49
2N5239	Si-N	S-L, 300/225V, 5A, 100W, >2MHz	23a	USA, Rca, Tix	BU606..608, BUX 16A..C, 2SC2624, ++
2N524(A)	Ge+B14333-P	NF/S, 45V, 0,5A, 0,225W, 1,5MHz	2a(B=case)	USA,Mot,Tix	ASY 76..77
2N5240	Si-N	=2N5239: 375/300V	23a		BU606..608, BUX 16B..C, 2SC2624, ++
2N5241	Si-N	S-L, 400/400V, 5A, 125W(Tc=62°)	23a	USA,Mot,Tix	BUX16C, BUX16C, BUX45, 2SD640, ++
2N5242	Si-P	S, 20V, 0,5A, 0,5W, >170MHz, <45/95ns	8a	Fch	2N3467..58, 2N5022..23, 2SA742,++
2N5243	Si-P	=2N5242: 30V	8a		2N3467..66, 2N5022..23, 2SA742,++
2N5244	Si-P	S, RadH, 40V, 0,1A, 0,36W, <55/150ns	2a	Fch,Itt,Sgs	—
2N5245	N-FET	VHF, 30V, Idss>5mA, Up<6V	7f	USA,Isi,Mot	BF 244..245, BFS 80, BFW11, 2N4416,++
2N5245	N-FET			Tho,Tix,++	—
2N5246	N-FET	VHF, 30V, Idss>1,5mA, Up<4V	7f		2SK107, 2SK161
2N5247	N-FET	VHF, 30V, Idss>8mA, Up<8V	7f		BF 244..245, BFW 10
2N5249	N-FET	VHF, 30V, Idss>4mA, Up<8V	7e	USA,Isi,Tix	BF 244..245, BFS 72, 2N3823
2N5249(A)	Si-N	NF, ra, 70V, 0,1A, 0,39W	7c	Gen,Sem,Sp	2SC1775(A), 2SC2240, 2SC2389, 2SC2459,+
2N525(A)	Ge-P	NF/S, 45V, 0,5A, 0,225W, 2MHz	2a(B=case)	USA,Mot,Tix	ASY 76..77
2N5250	Si-N	S-L, 125/100V, 90A, 350W, >10MHz	49m	USA	2N6309..11
2N5251	Si-N	=2N5250: 180/150V	49m		2N6309..11
2N5252	Si-N	S/Vid, 300/300V, 1A, 1W, >30MHz, B>40	2a	Ssi,Stc	BFQ 38..40, BSS48..49, 2N3439..40
2N5253	Si-N	=2N5252: B>80	2a		BFQ 38..40, BSS46..49, 2N3439..40
2N5254	Si-P	Dual, ra, 40V, 0,05A, 0,43W, >40MHz	TO-77P	Fch,Isi	BFX 11, 2N3726, 2N4015..16
2N5254..56/78	Si-P	=2N5254..58: 0,5W, >60MHz	TO-77		BFX 11, 2N3726, 2N4015..16
2N5255	Si-P	Dual, ra, 40V, 0,05A, 0,43W, >40MHz	TO-77P		BFX 11, 2N3726, 2N4015..16
2N5258	Si-P	Dual, ra, 40V, 0,05A, 0,43W, >40MHz	TO-77P		BFX 11, 2N3726, 2N4015..16+F14449
2N526(A)	Ge-P	NF/S, 45V, 0,5A, 0,225W, 2,5MHz	2a(B=case)	USA,Mot,Tix	ASY 76..77
2N5262	Si-N	S, 75V, 2A, 1W, 350MHz, 18/35ns	2a	USA,Rca	BSS 14, 2N3507
2N5263	Si-N	SMD, S, 30V, 0,025A, >1GHz	Chip	Amp	—
2N5264	Si-N	S-L, 400/180V, 7A, 87W, >50MHz	23a	USA	BU606..608, BUX 18B..C, 26C2658, ++
2N5265	P-FET	Uni, 80V, Idss>0,5mA, Up<3V	5n	Isi,Mot	—
2N5266	P-FET	Uni, 80V, Idss>0,8mA, Up<3V	5n	Isi,Mot	—
2N5267	P-FET	Uni, 80V, Idss>1,5mA, Up<6V	5n	Isi,Mot	2N5463..64
2N5268	P-FET	Uni, 80V, Idss>2,5mA, Up<6V	5n	Isi,Mot	2N5463..84
2N5269	P-FET	Uni, 80V, Idss>4mA, Up<8V	5n	Isi,Mot	2N5465
2N527(A)	Ge-P	NF/S, 45V, 0,5A, 0,225W, 3,5MHz	2a(B=case)	USA,Mot,Tix	ASY 76..77
2N5270	P-FET	Uni, 80V, Idss>7mA, Up<6V	5n	Isi,Mot	—
2N5271	Si-N	S, Avalanche, 280V, 5A(ss), 0,6W	2a	Mot,Sca	—
2N5272	Si-N	S, 40V, 0,2A, 0,36W, >500MHz, <23/28ns	2a	Sty	BSS 10..11, BSX 19..20, 2N2368..69(A),++
2N5273	Triac	200V, 25A, Igt/Ih<150/<100mA	21l	Tix	2N5806, BTX 94/200
2N5274	Triac	=2N5273: 400V	21l		2N5807, BTX 94/400
2N5275	Triac	=2N5273: 600V	21l		2N5809, BTX 94/600
2N5276	Si-N	S, RadH, 25V, 0,36W, >600MHz	2a	Tix	—
2N5277	N-FET	S, 150V, Idss>2,5mA, Up<7V	2b	Six,Tix	—
2N5278	N-FET	S, 150V, Idss>10mA, Up<10V	2b	Six,Tix	—
2N5279	Si-N	S/Vid, 400/300V, 1A, 1W, >15MHz	2a	Sca,Ssi,Stc	BFQ 40, BSS 49, 2N3439
2N526	Ge-P	NF/S, 40V, 1A, 2,5W, >4MHz	2e	Wes	2SB493
2N5280	Si-N	=2N5279: 15W	43m		(BD410, BUW 40(A,B), TIP 49..50,++)
2N5281	Si-P	S/Vid, 175V, 1A, 2W(Tc=100°), >20MHz	2a	Sca,Ssi,Stc	BFT 19(A,B), BFT 28A..C, 2N5415..16, ++
2N5262	Si-P	=2N5261: 325/300V	2a		BFT 19B, 2N5416, MJ5416
2N5284	Si-N	S-L, 120/100V, 5A, 50W(Tc=50°), >80MHz	49a	USA	—
2N5285	Si-N	S-L, 120/100V, 5A, 50W(Tc=50°), >70MHz	49a		—
2N5286	Si-P	S-L, 120/100V, 5A, 50W(Tc=50°), >80MHz	49a	USA	—
2N5287	Si-P	S-L, 120/100V, 5A, 50W(Tc=50°), >70MHz	49a		—

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2N5288	Si-N	S-L, 120/100V, 10A, 100W(Tc=50°), >30MHz	49a	USA	2N5542
2N5289	Si-N	S-L, 120/100V, 10A, 100W(Tc=50°), >40MHz	49a		2N5542
2N529	Ge-N/P	NF-komplementgep, 15V, 0,025A, β+C14444>15	2a	Csr,Etc	(AC127+AC128, AC127+AC152)
2N5290	Si-P	S-L, 120/100V, 10A, 100W(Tc=50°), >30MHz	49a	USA	—
2N5291	Si-P	S-L, 120/100V, 10A, 100W(Tc=50°), >40MHz	49a		—
2N5292	Si-P	S, RadH, 12V, 0,1A, 0,36W, >800MHz	2a	Fch,Spe,Sty	—
2N5293	Si-N	NF/S-L, 80V, 4A, 36W, >0,8MHz	17j	USA,Mic,Nsc	BD243B, BD537, BD539B, BD951,++
2N5293	Si-N			Rca,Tho,Tos	—
2N5294	Si-N	NF/S-L, 80V, 4A, 36W, >0,8MHz	17j		BD243B, BD537, BD539B, BD951, ++
2N5295	Si-N	NF/S-L, 80V, 4A, 36W, >0,8MHz	17j		BD243A, BD535, BD539A, BD949, ++
2N5296	Si-N	NF/S-L, 80V, 4A, 38W, >0,8MHz	17j		BD243A, BD535, BD539A, BD949, ++
2N5297	Si-N	NF/S-L, 80V, 4A, 36W, >0,8MHz	17j		BD243B, BD537, BD539B, BD951, ++
2N5296	Si-N	NF/S-L, 80V, 4A, 36W, >0,8MHz	17j		BD243B, BD537, BD539B, BD951,++
2N53	Ge-P	S, 50V, 8mA, 0,1W		Civ	(ASY48)
2N530	Ge-N/P	=2N529: β>20	2a	Csr,Etc	(AC127+AC128, AC127+AC152)
2N5301	Si-N	NF/S-L, 40V, 30A, 200W, >2MHz	23a	USA,Mot,Rca	BDY29, MJ802, 2N3771, 2SD630, 2SD797
2N5301	Si-N			Sgs,Tix,Tos	—
2N5302	Si-N	=2N5301: 80V	23a		BDY29, MJ802, 2SD797
2N5303	Si-N	=2N5301: 80V	23a		BDY29, MJ802, 2SD797
2N5304	Si-N	S-L, 50V, 10A, 25W(Tc=125°), >100MHz	49m	Mot,Stc	—
2N5305	Si-N-Darl	NF-V, 25V, 0,3A, 0,4W, B>2000, >60MHz	7c	USA,Mic,Nsc	BC517, BC617, MPS-A13..14, 2SD892,++
2N5308	Si-N-Darl	=2N5305: B>7000	7c		BC517, BC617, MPS-A13..14, 2SD892,++
2N5308A	Si-N-Darl	=2N5305: B>7000, ra	7c		—
2N5307	Si-N-Darl	NF-V, 40V, 0,3A, 0,4W, B>2000, >60MHz	5c		BC517, BC617, MPS-A25..29, 2SD892A,++
2N5308	Si-N-Darl	=2N5307: B>7000	5c		BC517, BC817, MPS-A25..29, 2SD892A,++
2N5308A	Si-N-Darl	=2N5307: B>7000,ra	5c		—
2N5309	Si-N	NF, 70V, 0,1A, 0,36W, B>80	7c	Gen,Sem,Spr	BC174, BC182, BC190, BC546,++
2N531	Ge-N/P	=2N529: β>25	2a	Csr,Etc	(AC127+AC126, AC127+AC152)
2N5310	Si-N	=2N5309: B>100	7c		BC174, BC182, BC190, BC548,++
2N5311	Si-N	=2N5309: B>250	7c		BC174, BC182, BC190, BC546,++
2N5312	Si-P	S-L, 80V, 10A, 50W(Tc=100°), >30MHz	49m	USA	2N5290..91
2N5313	Si-N	S-L, 80V, 10A, 50W(Tc=100°), >30MHz	49m	USA	2N5288..89
2N5314	Si-P	=2N5312: 100V	49m		2N5290..91
2N5315	Si-N	=2N5313: 100V	49m		2N52S8..89
2N5316	Si-P	=2N5312: Iso	49a		2N5290..91
2N5317	Si-N	=2N5313: Iso	49a		2N5288..89
2N5318	Si-P	=2N5312: Iso, 100V	49a		2N5290..91
2N5319	Si-N	=2N5313: Iso, 100V	49a		2N5288..89
2N532	Ge-N/P	=2N529: β>30	2a	Csr,Etc	(AC127+AC128, AC127+AC152)
2N5320	Si-N	NF/S, 100V, 2A, 10W(Tc=25°), <80/800ns	2a	USA,Rca,Sgs	BSS15, BSV84, 2N4239, 2SD854
2N5320	Si-N			Mot,Tix	—
2N5321	Si-N	=2N5320: 75V	2a		BSS15, BSV84, 2N4238..36, 2SD854
2N5322	Si-P	NF/S, 100V, 2A, 10W(Tc=25°), <100/1000ns	2a	USA,Rca,Sgs	BSS17
2N5322	Si-P			Mot,Tix	—
2N5323	Si-P	=2N5322: 75V	2a		BSS17..18, 2N4236
2N5324	Ge-P	TV-HA, 250V, 10A, 56W	23a	Gpd,Mot,Sam	AU113, AU213
2N5325	Ge-P	=2N5324: 325V	23a		AU106, AU109, AU111..112
2N5326	Si-N	S-L, 100V, 5A, 20W(Tc=100°), >80MHz	49a	USA,Tix	2N5002, 2N5004, 2N5284..85
2N5327	Si-N	S, 100V, 10A, 5W(Tc=100°), >100MHz	2a	USA,Tix	BUY82
2N5328	Si-N	S-L, 100V, 10A, 30W(Tc=100°), >100MHz	49a	USA,Tix	2N5348..49
2N5329	Si-N	S-L, 150V, 20A, 65W(Tc=100°), >80MHz	49a	USA,Tix	—
2N533	Ge-N/P	=2N529: β>35	2a	Csr,Etc	(AC127+AC128, AC127+AC152)
2N5330	Si-N	S-L, 150V, 30A, 80W(Tc=100°), >80MHz	49a	USA,Tix	—
2N5331	Si-N	S-L, 150V, 30A, 100W(Tc=100°), >80MHz	49a	USA,Tix	2N2825
2N5332	Si-P	S, RadH, 20V, 0,1A, 0,36W, >800MHz	2a	Mot,Tix	—
2N5333	Si-P	NF/S, 100V, 2A, 1W, 150/450ns	2a	USA,Tix	BSS17, 2N5322
2N5334	Si-N	NF/S, 80V, 3A, 6W(Tc=25°), <100/1050ns	2a	USA, Mot	BSX62..64, 2N4237..39, 2SC2214
2N5335	Si-N	=2N5334: 80V	2a		BSX63..64, 2N4236..39, 2SC2214
2N5336	Si-N	NF/S, 80V, 5A, 6W(Tc=25°), B>30	2a	USA,Mot,Nsc	BFT32..34, BUX34, BUY80, 2N4895..97
2N5336	Si-N			Sgs,Tix	—
2N5337	Si-N	=2N5336: B>80	2a		BFT32..34, BUX34, BUY80, 2N4895..97
2N5336	Si-N	=2N5336: 100V	2a		BFT33..34, BUX34, BUY80, 2N4895..97
2N5339	Si-N	=2N5336: 100V, B>80	2a		BFT33..34, BUX34, BUY80, 2N4895..97
2N534	Ge-P	NF/S, 50V, 0,025A, 0,025W	37e	Etc,Nsc,Phc	(ASY48, ASY77)
2N5344	Si-P	NF/S-L, 250/250V, 1A, 40W, >60MHz	22a	Mot,Stc	BUX66A..C, 2N6421, 2SA1009(A), 2SA1397
2N5345	Si-P	=2N5344: 300/300V	22a		BUX66A..C, 2N6421, 2SA1009(A), 2SA1397

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2N5346	Si-N	=2N5336: 7A, 60W	49a	USA, Mot	—
2N5347	Si-N	=2N5337: 7A, 60W	49a	USA, Mot	—
2N5348	Si-N	=2N5338: 7A, 60W	49a	USA, Mot	—
2N5349	Si-N	=2N5339: 7A, 60W	49a	USA, Mot	—
2N535(A,B)	Ge-P	NF/S, 20/20/20V, 0,02A, 0,05W, 2MHz	37e	Csr,Etc	(ASY26..27)
2N5350	Si-N	S-L, 125/100V, 350W, >10MHz			—
2N5351	Si-N	S-L, 180/150V, 350W, >10MHz			—
2N5354	Si-P	Uni, 25V, 0,3A, 0,36W, 250MHz, B>40	7c	USA,Mic,Nsc	BC327..326, BC636, BC638, BC640, ++
2N5355	Si-P	=2N5354: B>100	7c		BC327..328, BC636, BC638, BC640, ++
2N5356	Si-P	=2N5354: B>250	7c		BC327..328, BC636, BC638, BC640, ++
2N5357	Si-P	S-L, 300/300V, 3A 30W(Tc=75°), >50MHz	43m	Mot,Mic,Stc	(2SA1009(A), 2SA1238, 2SA1397)
2N5358	N-FET	Uni, ra, 40V, Idss>0,5mA, Up<3V	5m	USA,Mot,Tix	2N4339, 2SK83, 2SK193, 2SK195
2N5359	N-FET	Uni, ra, 40V, Idss>0,8mA, Up<4V	5m	USA,Mot,Tix	—
2N536	Ge-P	NF/S, 20/20/20V, 0,03A, 0,05W, 2MHz	37e	Etc	(ASY26..27)
2N5360	N-FET	Uni, ra, 40V, Idss>1,5mA, Up<4V	5m	USA,Mot,Tix	2N5246
2N5361	N-FET	Uni, ra, 40V, Idss>2,5mA, Up<6V	5m	USA,Mot,Tix	BF256A, BFS71, 2N3822, 2N4221, 2N5458
2N5362+A14531	N-FET	Uni, ra, 40V, Idss>4mA, Up<7V	5m	USA,Mot,Tix	BF256A, BFS80, BFW11, 2N4416, ++
2N5363	N-FET	Uni, ra, 40V, Idss>7mA, Up<8V	5m	USA,Mot,Tix	BFW10
2N5364	N-FET	Uni, ra, 40V, Idss>9mA, Up<8V	5m	USA,Mot,Tix	BF244C..245C, BFW10
2N5365	Si-P	=2N5354: 40V	7c	USA,Mic,Nsc	BC327, BC638, BC638, BC640, ++
2N5366	Si-P	=2N5355: 40V	7c	USA,Mic,Nsc	BC327, BC638, BC638, BC640, ++
2N5367	Si-P	=2N5356: 40V	7c	USA,Mic,Nsc	BC327, BC638, BC638, BC640, ++
2N5368	Si-N	Uni, 60V, 0,5A, 0,36W, <40/350ns	7a	Gen,Mic,Nsc	BC337A, BC637, BSV59, 2N2221..22(A)++
2N5368	Si-N			Sem,Spr	—
2N5369	Si-N	Uni, 60V, 0,5A, 0,36W, <40/350ns	7a		BC337A, BC637, BSV59, 2N2221..22(A)++
2N537	Ge-P	VHF/UHF, 30V, 0,1A, 600MHz	2a	Wes	(AF139, AF239(S))
2N5370	Si-N	Uni, 60V, 0,5A, 0,36W, <40/400ns	7a		BC337A, BC637, BSV59, 2N2221..22(A)++
2N5371	Si-N	Uni, 40V, 0,5A, 0,36W, <40/400ns	7a		BC337, BC637, BSV59, 2N2221..22(A), ++
2N5372	Si-P	Uni, 60V, 0,5A, 0,36W, <50/150ns	7a	Gen,Mic,Nsc	BC327A, BC638, BSW24, 2N2906..07(A)++
2N5372	Si-P			Sem,Spr	—
2N5373	Si-P	Uni, 60V, 0,5A, 0,36W, <50/150ns	7a		BC327A, BC638, BSW24, 2N2906..07(A)++
2N5374	Si-P	Uni, 60V, 0,5A, 0,36W, <50/175ns	7a		BC327A, BC638, BSW24, 2N2906..07(A)++
2N5375	Si-P	Uni, 40V, 0,5A, 0,36W, <50/175ns	7a		BC327, BC638, BSW24, 2N2906..07(A), ++
2N5376	Si-N	Uni, 60V, 0,5A, 0,38W, >300MHz, B>120	7a	Itt,Sem,Spr	BC337A, BC637, BSV59, 2N2221..22(A)++
2N5377	Si-N	Uni, 60V, 0,5A, 0,38W, >300MHz, B>100	7a	Itt,Sem,Spr	BC337A, BC637, BSV59, 2N2221..22(A)++
2N5378	Si-P	Uni, 40V, 0,5A, 0,38W, >200MHz, B>120	7a	Itt,Sem,Spr	BC327A, BC638, BSW24, 2N2906..07(A)++
2N5379	Si-P	Uni, 40V, 0,5A, 0,38W, >200MHz, B>100	7a	Itt,Sem,Spr	BC327A, BC638, BSW24, 2N2906..07(A)++
2N538(A,M)	Ge-P	S-L, 80V, 3,5A, 34W, B>20	37b	Gpd,Sem,Stc	—
2N5380	Si-N	Uni, 60V, 0,2A, 0,36W, <70/225ns	7a	Itt,Sem,Spr	BC546, BSV59, BSX49, 2N2221..22(A), ++
2N5361	Si-N	Uni, 60V, 0,2A, 0,36W, <70/250ns	7a	Itt,Sem,Spr	BC546, BSV59, BSX49, 2N2221..22(A), ++
2N5382	Si-P	Uni, 40V, 0,2A, 0,38W, <70/260ns	7a	Itt,Sem,Spr	BC307, BC556, BSW24, 2N2906..07(A), ++
2N5383	Si-P	Uni, 40V, 0,2A, 0,38W, <70/300ns	7a	Itt,Sem,Spr	BC307, BC556, BSW24, 2N2906..07(A), ++
2N5384	Si-P	S-L, 100/80V, 5A, 30W(Tc=100°)	50g	USA,Tix	2N5003, 2N5005, 2N5286..87
2N5385	Si-P	=2N5384:	≈49m	USA,Tix	2N5003, 2N5005, 2N5286..87
2N5386	Si-P	S-L, 100/80V, 12A, 50W(Tc=100°)	49m	USA,Tix	2N5290..91
2N5387	Si-N	S-L, 200/200V, 7,5A, 100W(Tc=100°)	49m	Sol,Stc,Tix	2N5540
2N5388	Si-N	=2N5387: 250/250V	49m		2N5540
2N5389	Si-N	=2N5387: 300/300V	49m		2N5540
2N539(A)	Ge-P	=2N538: B>30	37b	Gpd,Sem,Stc	—
2N5390	Si-N-Darl	S, 120V, 2A, 1W, B>2000	5	USA,Tix	—
2N5391	N-FET	Uni, ra, 70V, Idss>0,5mA, Up<2V	2b	Sol,Tsc	—
2N5392	N-FET	Uni, ra, 70V, Idss>1mA, Up<2,5V	2b	Sol,Tsc	—
2N5393	N-FET	Uni, ra, 70V, Idss>2,5mA, Up<3V	2b	Sol,Tsc	—
2N5394	N-FET	Uni, ra, 70V, Idss>4mA, Up<4V	2b	Sol,Tsc	—
2N5395	N-FET	Uni, ra, 70V, Idss>5,5mA, Up<4V	2b	Sol,Tsc	—
2N5396	N-FET	Uni, ra, 70V, Idss>7,5mA, Up<5V	2b	Sol,Tsc	—
2N5397	N-FET	VHF/UHF, 25V, Idss>10mA, Up<6V	5k	USA,Isi,Tix	BF256C, 2N5486
2N5398	N-FET	VHF/UHF, 25V, Idss>5mA, Up<6V	5k	USA,Isi,Tix	BF256A,B, 2N5486
2N5399	Si-N	S, RadH, 25V, 0,1A, 0,36W, >600MHz	2a	Tix	—
2N54	Ge-P	NF, 45V, 10m, 0,2W	24e	Whs	ASY48, 2SB56A
2N540(A)	Ge-P	=2N538: B>45	37b	Gpd,Sem,Stc	—
2N5400	Si-P	Uni, 130V, 0,6A, 0,625W, >100MHz	7e	USA,EUR,Tos	BF491, 2SA840, 2SA1221..22, 2SA1319, ++
2N5401	Si-P	=2N5400: 160V	7e		BF491..493, 2SA1221..22, 2SA1319, ++
2N5404	Si-P	S, 80V, 5A, 1W, >40MHz, B>20	2a	USA,Tix	BFT35..37, BSS48, 2N6190..93
2N5405	Si-P	=2N5404: 100V	2a		BFT38..37, 2N6192..93
2N5406	Si-P	=2N5404: B>40	2a		BFT35..37, BSS46, 2N6190..93

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2N5407	Si-P	=2N5404: 100V, B>40	2a		BFT36..37, 2N6192..93
2N5408	Si-P	S-L, 80V, 5A, 30W(Tc=100°), B>20	49m		2N5003, 2N5005, 2N5286..87
2N5409	Si-P	=2N5408: 100V	49m		2N5003, 2N5005, 2N5286..87
2N541(A)	Si-N	NF/HF, 15V, 0,025A, 0,2W, >10MHz	2a	USA, Tix	BC168, BC183, BC236, BC548, ++
2N5410	Si-P	=2N5408: B>40	49m		2N5003, 2N5005, 2N5286..87
2N5411	Si-P	=2N5408: 100V, B>40	49m		2N5003, 2N5005, 2N5286..87
2N5412	Si-N	S-L, 80V, 15A, 100W, >80MHz	49m	USA, Tix	(2N2615..16, 2N2619..20)
2N5413	Si-N	S, 80V, 2A, 1W, >250MHz, <42/85ns	2a	Csr, Sca, Ssi	BSS14, 2N5262
2N5414	Si-N	=2N5413: 80V	2a		BSS14, 2N5262
2N5415(S)	Si-P	S/Vid, 200V, 1A, 10W(Tc=25°), >15MHz	2a	USA, EUR	BFT19(A,B), BFT28A..C), MJ5415..16
2N5416	Si-P	S/Vid, 350V, 1A, 10W(Tc=25°), >50MHz	2a		BFT19B, M5416
2N5417	Si-N	S, RadH, 40V, 0,5A, 0,5W, >250MHz	2a	Sty	—
2N5418	Si-N	Uni, 25V, 0,5A, 0,4W, 250MHz, B>40	7c	USA, Gen, Mic	BC337..338, BC635, BC637, BC639, ++
2N5419	Si-N	=2N5418: B>100	7c		BC337..338, BC635, BC637, BC639, ++
2N542(A)	Si-N	=2N541: 30V	2a	USA, Tix	BC168, BC183, BC236, BC548, ++
2N5420	Si-N	=2N5418: B>250	7c		BC337..F14614338, BC635, BC637, BC639, ++
2N5421	Si-N	VHF-Tr/E, 36V, 0,5A, PQ=1W(175MHz)	2a	Itt, Sem, Tix	BFQ42, BFR98, BLW16, BLY61
2N5422	Si-N	VHF-Tr/E, 36V, 1A, PQ=2W(175MHz)	2a	Itt, Sem, Tix	BFQ43, 2N6255
2N5423	Si-N	VHF-L, 36V, 2A, PQ=5W(175MHz)	49a	Itt, Sem, Tix	BLW35, BLY79
2N5424(A)	Si-N	VHF-L, 36V, 4A, PQ=13W(175MHz)	49a	Itt, Sem, Tix	BLW36
2N5425	Si-N-Darl	S-L, 60V, 5A, 32,5W(Tc=70°), B>500	2a	Fch, Sca, Sem	—
2N5426	Si-N-Darl	=2N5425: B>1000	2a		—
2N5427	Si-N	=2N5336: 7A, 40W	22a	USA, Mot, Sgs	MJE15028, 2N6316, 2N6372, 2SC3254
2N5428	Si-N	=2N5337: 7A, 40W	22a	USA, Mot, Sgs	MJE15028, 2N6316, 2N6372, 2SC3254
2N5429	Si-N	=2N5338: 7A, 40W	22a	USA, Mot, Sgs	MJE15028
2N543(A)	Si-N	=2N541: 50V	2a	USA, Tix	BC167, BC182, BC237, BC547, ++
2N5430	Si-N	=2N5339: 7A, 40W	22a	USA, Mot, Sgs	MJE15028
2N5431	UJT-P	Ip<0,4µA, Iv>2mA	2e	Mot	—
2N5432	N-FET	S, 25V, 0,4A, Idss>150mA, Up<10V	2b	USA, Tho, Tix	—
2N5433	N-FET	S, 25V, 0,4A, Idss>100mA, Up<9V	2b	USA, Tho, Tix	—
2N5434	N-FET	S, 25V, 0,4A, Idss>30mA, Up<4V	2b	USA, Tho, Tix	—
2N5435	Ge-P	NF/S-L, 60V, 60A, 120W, B>20	23a	Gpd, Mot	MP5435
2N5436	Ge-P	=2N5435: 110V	23a		MP5436
2N5437	Ge-P	=2N5435: 140V	23a		MP5437
2N5438	Ge-P	=2N5435: B>40	23a		MP5438
2N5439	Ge-P	=2N5435: 110V, B>40	23a		MP5439
2N544	Ge-P	HF, 18V, 0,01A, 0,08W, 30MHz	1g	Rca, Syl+E5152	AF124..126, AF200
2N544/12,/33	Ge-P	=2N544: 24V	5g	Syl	AF124..126, AF200
2N5440	Ge-P	=2N5435: 140V, B>40	23a		MP5440
2N5441	Triac	200V, 40A, Igt/Ih<100/<60mA	29l	Mot, Rca	T6400B
2N5442	Triac	=2N5441: 400V	29l		T6400D
2N5443	Triac	=2N5441: 600V	29l		T6400M
2N5444	Triac	=2N5441:	21l		T6401B
2N5445	Triac	=2N5442:	21l		T6401D
2N5446	Triac	=2N5443:	21l		T6401M
2N5447	Si-P	Uni, 40V, 0,2A, 0,3W, >100MHz	7a	USA, EUR, Mic	BC327, BC636, BC636, BC640, ++
2N5448	Si-P	Uni, 50V, 0,2A, 0,3W, >100MHz	7a		BC327, BC636, BC636, BC640, ++
2N5449	Si-N	Uni, 50V, 0,8A, 0,36W, >100MHz	7a	USA, EUR, Mic	BC337, BC636, BC637, BC639, ++
2N545	Si-N	NF/S, 80V, 0,8A, 0,6W(Ta=100°), >4MHz	2a	USA	BC140..141, BC300..302, 2N3053, ++
2N5450	Si-N	Uni, 50V, 0,8A, 0,36W, >100MHz	7a		BC337, BC635, BC637, BC639, ++
2N5451	Si-N	Uni, 40V, 0,8A, 0,36W, >100MHz	7a		BC337, BC635, BC637, BC639, ++
2N5452	N-FET	Dual, ra, 50V, Idss>0,5mA, Up<4,5V	TO-71	Isi, Nsc, Six	BFQ10..16, 2N3921..22, 2N3954..59
2N5452	N-FET			Sol	—
2N5453	N-FET	Dual, ra, 50V, Idss>0,5mA, Up<4,5V	TO-71		BFQ10..18, 2N3921..22, 2N3954..59
2N5454	N-FET	Dual, ra, 50V, Idss>0,5mA, Up<4,5V	TO-71		BFQ10..16, 2N3921..22, 2N3954..59
2N5455	Si-P	S, 15V, 0,3A, 0,34W, <30/40ns	2a	Fch	BSX36
2N5456	Si-P	S, 25V, 0,3A, 0,34W, <30/40ns	2a		BSX36
2N5457	N-FET	Uni, sym, 25V, Idss>1mA, Up<6V	7d	Isi, Mic, Mot	2SK248, 2SK330
2N5457	N-FET			Nsc, Six, ++	—
2N5458	N-FET	Uni, sym, 25V, Idss>2mA, Up<7V	7d		BFS71, 2N3822, 2N4221, 2N5361, ++
2N5459	N-FET	Uni, sym, 25V, Idss>4mA, Up<8V	7d		BF244B..245B, BFS72, 2N3823, 2N4222, ++
2N546	Si-N	NF/S, 30V, 0,8A, 0,6W(Ta=100°), >4MHz	2a	USA	BC140..141, BC300..302, 2N3053, ++
2N5460	P-FET	Uni, ra, 40V, Idss>1mA, Up<6V	7c	Isi, Mot, Nsc	2SJ103, 2SJ105
2N5460	P-FET			Phi, Sol	—
2N5461	P-FET	Uni, ra, 40V, Idss>2mA, Up<7,5V	7c		BF320B
2N5462	P-FET	Uni, ra, 40V, Idss>4mA, Up<9	7c		2N4360

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2N5463	P-FET	=2N5460: 60V	7c		—
2N5464	P-FET	=2N5461: 60V	7c		—
2N5465	P-FET	=2N5462: 60V	7c		—
2N5465	Si-N	S-L, 500/400V, 3A, 140W, >2,5MHz	23a	USA	BUX15, BUX45, 2SC3041, 2SD640, ++
2N5467	Si-N	=2N5465: 700/400V	23a		BUS11(A), BUX47(A), BUX82..63, ++
2N5468	Si-N	=2N5466: 70W	22a		BUT93, BUY63..64, MJ4380..81, ++
2N5469	Si-N	=2N5466: 700/400V, 70W	22a		BUT11(A), BUV46(A), MJ4381, 3SC3490++
2N547	Si-N	NF/S, 60V, 0,8A, 0,8W(Ta=100°), >4MHz	2a	USA	BC140..141, BC300..302, 2N3053, ++
2N5470	Si-N	UHF-A/Tr, 55V, 0,2A, PQ=2W(1GHz)	Koax	Rca	2N5920
2N5471	P-FET	Uni, sym, 40V, Idss>0,02mA, Up<4V	5n	Mot	2N5797
2N5472	P-FET	Uni, sym, 40V, Idss>0,05mA, Up<4V	5n	Mot	2N5797
2N5473	P-FET	Uni, sym, 40V, Idss>0,1mA, Up<6V	5n	Mot	2N5798
2N5474	P-FET	Uni, sym, 40V, Idss>0,2mA, Up<7V	5n	Mot	2N5798
2N5475	P-FET	Uni, sym, 40V, Idss>0,4mA, Up<8V	5n	Mot	BF320A, 2N3909, 2N3820, 2N5799
2N5476	P-FET	Uni, sym, 40V, Idss>0,8mA, Up<9V	5n	Mot	2N5800
2N5477	Si-N	=2N5336: 7A, 60W	49m	USA, Mot	(2N3487..92)
2N5478	Si-N	=2N5337: 7A, 80W	49m	USA, Mot	(2N3487..92)
2N5479	Si-N	=2N5338: 7A, 80W	49m	USA, Mot	(2N3468..89, 2N3491..92)
2N548	Si-N	NF/S, 30V, 0,8A, 0,6W(Ta=100°), >4MHz	2a	USA	BC140..141, BC300..302, 2N3053, ++
2N5460	Si-N	=2N5339: 7A, 60W	49m	USA, Mot	(2N3488..89, 2N3491..92)
2N5481	Si-N	UHF-Tr/E, 50V, 0,2A, 5W, 3GHz	55r	Trw	BFQ88
2N5482	Si-N	UHF-Tr/E, 50V, 0,35A, 10W, 3GHz	55r	Trw	BFQ88, BFQ138, BFT99
2N5483	Si-N	UHF-Tr/E, 45V, 0,7A, 20W, 3GHz	55r	Trw	BFQ136
2N5464	N-FET	VHF/UHF, 25V, Idss>1mA, Up<3V	7d	USA, EUR, Mic	BF410A, B
2N5485	N-FET	VHF/UHF, 25V, Idss>4mA, Up<4V	7d		BF256A, B
2N5486	N-FET	VHF/UHF, 25V, Idss>8mA, Up<6V	7d		BF256B, C, 2N5397
2N5487	Si-N	S, 120V, 5A, 15W(Tc=25°), <125/450ns	2a	USA, Tiw	BUX34, BUY60, 2N4895..97
2N5467-1	Si-N	S, 120V, 5A, 1,2W, <125/450ns	2a		BUX34, BUY60, 2N4895..97
2N5487-3	Si-N	S, 120V, 5A, 1,5W, <125/450ns	2a°		BUX34, BUY60, 2N4895..97
2N5488	Si-N	S, 150V, 5A, 15W(Tc=25°), <125/550n	2a	USA, Tiw	BUY60, 2N4897
2N5488-1	Si-N	S, 150V, 5A, 1,2W, <125/550n	2a		BUY60, 2N4897
2N5488-3	Si-N	S, 150V, 5A, 1,5W, <125/550n	2a°		BUY60, 2N4897
2N5489	Si-N	S-L, 125/100V, 40A, 300W, >0,5MHz	49m	USA	2N6309..11
2N549	Si-N	NF/S, 60V, 0,8A, 0,6W(Ta=100°), >4MHz	2a	USA	BC140..141, BC300..302, 2N3053, ++
2N5490	Si-N	NF/S-L, 60V, 7A, 50W, >0,8MHz	17j	USA, Mot, Tho	BD243A, BD543A, BD797, BD607, ++
2N5491	Si-N	=2N5490	17j		BD243A, BD543A, BD797, BD607, ++
2N5492	Si-N	NF/S-L, 75V, 7A, 50W, >0,8MHz	17j		BD243B, BD543B, BD799, BD809, ++
2N5493	Si-N	=2N5492	17j		BD243B, BD543B, BD799, BD809, ++
2N5494	Si-N	NF/S-L, 60W, 7A, 50W, >0,6MHz	17j		BD243A, BD543A, BD797, BD607, ++
2N5495	Si-N	=2N5495	17j		BD243A, BD543A, BD797, BD607, ++,
2N5496	Si-N	NF/S-L, 90V, 7A, 50W, >0,8MHz	17j		BD243B, BD543C, BD801, 2SD550, ++
2N5497	Si-N	=2N5496	17j		BD243B, BD543C, BD801, 2SD550, ++
2N5498	Si-N	S-L, 150/130V, 15A, 200W, >1MHz	23a	USA, Fch	BDX50, BUW57..56, BUX40, 2N3773, ++
2N55	Ge-P	NF, 45V, 10m, 0,2W	24e	Whs	ASY46, 2SB56A
2N550	Si-N	NF/S, 30V, 0,8A, 0,8W(Ta=100°), >4MHz	2a	USA	BC140..141, BC300..302, 2N3053, ++
2N5505	P-FET	Dual, ra, 30V, Idss<7mA, Up<4V	TO-71	Tac	—
2N5506	P-FET	Dual, 30V, Idss<7mA, Up<4V	TO-71		—
2N5507	P-FET	Dual, 30V, Idss<7mA, Up<4V	TO-71		—
2N5508	P-FET	Dual, 30V, Idss<7mA, Up<4V	TO-71		—
2N5509	P-FET	Dual, 30V, Idss<7mA, Up<5V	TO-71		—
2N551	Si-N	NF/S, 60V, 0,8A, 0,6W(Ta=100°), >4MHz	2a	USA	BC140..141, BC300..302, 2N3053, ++
2N5510	P-FET	Dual, 30V, Idss<5mA, Up<4V	TO-71		—
2N5511	P-FET	Dual, 30V, Idss<5mA, Up<4V	TO-71		—
2N5512	P-FET	Dual, 30V, Idss<5mA, Up<4V	TO-71		—
2N5513	P-FET	Dual, 30V, Idss<5mA, Up<4V	TO-71		—
2N5514	P-FET	Dual, 30V, Idss<5mA, Up<5V	TO-71		—
2N5515	N-FET	Dual, ra, 40V, Idss<0,5mA, Up<4V	TO-71	Isi, Nsc, Six	BFQ10..18, 2N5045..47, 2N5452..54
2N5515	N-FET			Sol, Tix	—
2N5516	N-FET	Dual, ra, 40V, Idss<0,5mA, Up<4V	TO-71		BFQ10..18, 2N5045..47, 2N5452..54
2N5517	N-FET	Dual, ra, 40V, Idss<0,5mA, Up<4V	TO-71		BFQ10..16, 2N5045..47, 2N5452..54
2N5518	N-FET	Dual, ra, 40V, Idss<0,5mA, Up<4V	TO-71		BFQ10..16, 2N5045..47, 2N5452..54
2N5519	N-FET	Dual, ra, 40V, Idss<0,5mA, Up<4V	TO-71		BFQ10..16, 2N5045..47, 2N5452..54
2N552	Si-N	NF/S, 30V, 0,8A, 0,6W(Ta=100°), >4MHz	2a	USA	BC140..141, BC300..302, 2N3053, ++
2N5520	N-FET	Dual, ra, 40V, Idss<0,5mA, Up<4V	TO-71		BFQ10..16, 2N5045..47, 2N5452..54
2N5521	N-FET	Dual, ra, 40V, Idss<0,5mA, Up<4V	TO-71		BFQ10..16, 2N5045..47, 2N5452..54
2N5522	N-FET	Dual, ra, 40V, Idss<0,5mA, Up<4V	TO-71		BFQ10..16, 2N5045..47, 2N5452..54

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2N5523	N-FET	Dual, ra, 40V, Idss<0,5mA, Up<4V	TO-71		BFQ10..16, 2N5045..47, 2N5452..54
2N5524	N-FET	Dual, ra, 40V, Idss<0,5mA, Up<4V	TO-71		BFQ10..16, 2N5045..47, 2N5452..54
2N5525	Si-N-Darl	Uni, 40V, 0,2A, 0,36W, B>5000	7c	Tix	BC517, BC617, BC875, MPS-A25..26,++
2N5526	Si-N-Darl	=2N5525: B>1000	7c		BC517, BC617, BC875, MPS-A25..26,++
2N5527	Si-N	S-L, RadH, 60V, 5A, 5W(Tc=25°), >200MHz	2a	Sol,Ssi,Stc	—
2N5528	Si-N	=2N5527: RadH, 10A, 35W	49m		—
2N5529	Si-N	=2N5527: RadH, 10A, 35W	49m		—
2N553	Ge-P	NF/S-L, 80V, 4A, 35W	23a	USA	AL102..103, AUY21..22, 2N1546..48,++
2N5530	Si-N	=2N5527: RadH, 10A, 35W	49a		—
2N5531	Si-N	S-L, RadH, 90V, 5A, 5W(Tc=25°), >200MHz	2a	Sol,Ssi,Stc	—
2N5532	Si-N	=2N5531: RadH, 10A, 35W	49m		—
2N5533	Si-N	=2N5531: RadH, 10A, 35W	49m		—
2N5534	Si-N	=2N5531: RadH, 10A, 35W	49a		—
2N5535	Si-N	S-L, RadH, 80V, 20A, 50W, >150MHz	49m	Sol,Ssi,Stc	—
2N5536	Si-N	=2N5535: RadH	49a		—
2N5537	Si-N	=2N5535: RadH, 90V	49m		—
2N5538	Si-N	=2N5535: RadH, 90V	49a		—
2N5539	Si-N	S-L, 175V, 20A, 100W(Tc=100°), >20MHz	49m	Sol,Ssi,Stc	2N2818, 2N2822
2N554	Ge-P	NF/S-L, 15V, 3A, 40W	23a	USA, Mot	AD149, AUY19..20, 2N2137..46,++
2N5540	Si-N	S-L, 325V, 10A, 50W(Tc=100°), >20MHz	49m	Sol,Ssi,Stc	—
2N5541	Si-N	S-L, 175V, 5A, 8,75W(Tc=100°), >20MHz	2a	Sol,Ssi,Stc	BUY48..49
2N5542	Si-N	S-L, 175V, 10A, 50W(Tc=100°), >20MHz	49m	Sol,Ssi,Stc	—
2N5543	N-FET	S, 300V, Idss>2mA, Up<15V	2b	Tdy,Tix	2N4882
2N5544	N-FET	S, 200V, Idss>2mA, Up<15V	2b	Tdy,Tix	2N4883
2N5545	N-FET	Dual, 50V, Idss>0,5mA, Up<4,5V	TO-71	Nsc,Six,Sol	BFQ10..16, 2N5045..47, 2N5452..54
2N5545	N-FET			Tix	—
2N5546	N-FET	Dual, 50V, Idss>0,5mA, Up<4,5V	TO-71		BFQ10..16, 2N5045..47, 2N5452..54
2N5547	N-FET	Dual, 50V, Idss>0,5mA, Up<4,5V	TO-71		BFQ10..16, 2N5045..47, 2N5452..54
2N5548	MOS-P-FET-e	Chopper, 25V, Idss<10nA, Up<5V	7b	Tix	—
2N5549	N-FET	VHF/S, 40V, Idss>10mA, Up<6V	2b	Tix	BF256C, BF348, BFT10, 2N5397, 2N5486
2N555	Ge-P	=2N554: 30V	23a	USA, Mot	AD149, AUY19..20, 2N2137..46, ++
2N5550	Si-N	Vid, 160V, 0,6A, 0,625W, >100MHz	7e	USA,EUR,Tos	BF391..393, BFP22, MPS-A42..43,++
2N5551	Si-N	=2N5550: 180V	7e		BF391..393, BFP22, MPS-A42..43,++
2N5552	Si-N	S-L, 120V, 10A, 15W(Tc=25°), >30MHz	2a	USA,Nsc,Trw	BUY62, (2SC2527)
2N5552-1	Si-N	=2N5552:	2a		BUY62, (2SC2527)
2N5552-2(-4)	Si-N	=2N5552:	2a*		BUY62, (2SC2527)
2N5555	N-FET	S, sym, 25V, Idss>15mA, Up<5V	7d	USA,Mot,Nsc	2N4092
2N5556	N-FET	Uni, ra, 30V, Idss>0,5mA, Up<4V	5k	USA,Mot,Nsc	BFS70, 2N3821, 2N4220, 2SK104, 2SK301
2N5557	N-FET	Uni, ra, 30V, Idss>2mA, Up<5V	5k	USA,Mot,Nsc	2SK107
2N5558	N-FET	Uni, ra, 30V, Idss>4mA, Up<6V	5k	USA,Mot,Nsc	BFS80, BFW11, 2N4416, 2N5362,++
2N5559	Si-N	S-L, 150/120V, 10A, 100W, >0,8MHz	23a	Sol,Ssi,Tra	BD745E, BDX11, 2N3442, 2SD1047
2N556	Ge-N	NF/S, 25V, 0,2A, 0,1W	2a	USA	AC127, ASY28..29, ASY73..75
2N5560	Si-N	S-L, 175/120V, 30A, 150W, >40MHz	49m		2N6324..25
2N5561	N-FET	Dual, ra, 50V, Idss<10mA, Up<3V	TO-71	Nsc,Sol,Tsc	—
2N5562	N-FET	Dual, ra, 50V, Idss<10mA, Up<3V	TO-71		—
2N5563	N-FET	Dual, ra, 50V, Idss<10mA, Up<3V	TO-71		—
2N5564	N-FET	Dual, ra, 40V, Idss>5mA, Up<3V	TO-71	Isi,Mic,Nsc	—
2N5564	N-FET			Sol	—
2N5565	N-FET	Dual, ra, 40V, Idss>5mA, Up<3V	TO-71		—
2N5566	N-FET	Dual, ra, 40V, Idss>5mA, Up<3V	TO-71		—
2N5567	Triac	200V, 10A, Igt/Ih<40/<30mA	29l	Mot,Rca	T4101B
2N5568	Triac	=2N5567: 400V	29l		T4101D
2N5569	Triac	=2N5567:	21l		T4111B
2N557	Ge-N	NF/S, 20V, 0,2A, 0,1W	2a	USA	AC127, ASY28..29, ASY73..75
2N5570	Triac	=2N5568:	21l		T4111D
2N5571	Triac	200V, 15A, Igt/Ih<60/<75mA	29l	Mot,Rca	2N6157, T6400B, 2N5441
2N5572	Triac	=2N5571: 400V	29l		2N6158, T6400D, 2N5442
2N5573	Triac	=2N5571:	21l		T6411B, 2N6160, T6410B, 2N5444
2N5574	Triac	=2N5572:	21l		T6411D, 2N6161, T6410D, 2N5445
2N5575	Si-N	S-L, 70/50V, 60A, 300W, >0,4MHz	23a	Rca,Stc,Tra	—
2N5576	Si-N	S-L, 70/50V, 60A, 300W, >0,4MHz	23a	Rca,Stc,Tra	—
2N5577	Si-N	S-L, 70/50V, 60A, 300W, >0,4MHz	23a	Rca,Stc,Tra	—
2N5578	Si-N	S-L, 90/70V, 60A, 300W, >0,4MHz	23a	Rca,Stc,Tra	—
2N5579	Si-N	S-L, 90/70V, 60A, 300W, >0,4MHz	23a	Rca,Stc,Tra	—
2N558	Ge-N	NF/S, 15V, 0,2A, 0,1W	2a	USA	AC127, ASY26..29, ASY73..75
2N5580	Si-N	S-L, 90/70V, 60A, 300W, >0,4MHz	23a	Rca,Stc,Tra	—

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2N5581	Si-N	=2N2221A: 0,5W	2a	USA, Mot	→2N2221A
2N5582	Si-N	=2N2222A: 0,5W	2a	USA, Mot	→2N2222A
2N5583	Si-P	UHF-A/Tr, 30V, 0,5A, 1W, >1300MHz	2a	Mot	—
2N5584	Si-N	S-L, 225/180V, 30A, 100W(Tc=100°), >70MHz	49m	USA, Tiw	(2N6324..25)
2N5587	Si-N	S-L, 120/120V, 80A, 300W, >0,5MHz	49m	Sol, Ssi, Stc	2N6309..11
2N5588	Si-N	=2N5587: 160/180V	49m		—
2N5589	Si-N	VHF-L, 36V, 0,6A, PQ=3W(175MHz)	55r	Mot, Tho	BLY85, 2N6080
2N559	Ge-P	S, 15V, 0,05A, 0,15W, 100/37ns	2a	USA, Mot	ASZ21, 2N705(A), 2N2835, 2N2955..57
2N5590	Si-N	VHF-L, 36V, 2A, PQ=10W(175MHz)	55r	Mot, Tho, Tix	BLW19, BLW37, MRF208, MRF212
2N5591	Si-N	VHF-L, 36V, 4A, PQ=25W(175MHz)	55r		BLY89, MRF209, MRF238, 2N6082..83
2N5592	N-FET	Uni, 50V, Idss>1mA, Up<5V	5k	Sol	2N5360, 2N5246, 2SK107, 2SK161
2N5593	N-FET	Uni, 50V, Idss>1mA, Up<5V	5k	Sol	2N5360, 2N5246, 2SK107, 2SK161
2N5594	N-FET	Uni, 50V, Idss>1mA, Up<5V	5k	Sol	2N5360, 2N5246, 2SK107, 2SK161
2N5595	Si-N	UHF-L, 55V, 1,2A, 30W, >1500MHz	55r	Trw	—
2N5596	Si-N	UHF-L, 55V, 2,5A, 45W, >1500MHz	55r	Trw	—
2N5597	Si-P	NF/S-L, 80V, 2A, 20W, >80MHz	22a	USA, Tix	2SA1078..1079, 2SA1268
2N5598	Si-N	NF/S-L, 80V, 2A, 20W, >80MHz	22a	USA, Tix	2SC2528..2529, 2SC3252
2N5599	Si-P	NF/S-L, 100V, 2A, 20W, >50MHz	22a	USA, Tix	2SA1078..1079
2N56	Ge-P	NF, 45V, 10mA+C14776, 0,2W	24e	Whs	ASY48, 2SB56A
2N560	Si-N	NF/S, 60V, 0,1A, 0,5W, <60/50ns	2a	USA	2N3722..23, 2N3725, 2SC1385
2N5600	Si-N	NF/S-L, 100V, 2A, 20W, >50MHz	22a	USA, Tix	2SC2528..2529
2N5601	Si-P	NF/S-L, 100V, 2A, 20W, >60MHz	22a	USA, Tix	2SA1078..1079
2N5602	Si-N	NF/S-L, 100V, 2A, 20W, >60MHz	22a	USA, Tix	2SC2528..2529
2N5603	Si-P	NF/S-L, 120V, 2A, 20W, >50MHz	22a	USA, Tix	2SA1078..1079
2N5604	Si-N	NF/S-L, 120V, 2A, 20W, >50MHz	22a	USA, Tix	2SC2528..2529
2N5605	Si-P	NF/S-L, 80V, 5A, 25W, >70MHz	22a	USA, Tix	MJE15029, MJE15031, 2SA1269
2N5606	Si-N	NF/S-L, 80V, 5A, 25W, >70MHz	22a	USA, Tix	MJE15028, ME15030, 2SC3253
2N5607	Si-P	NF/S-L, 100V, 5A, 25W, >60MHz	22a	USA, Tix	MJE15029, MJE15031
2N5608	Si-N	NF/S-L, 100V, 5A, 25W, >60MHz	22a	USA, Tix	MJE15028, ME15030
2N5609	Si-P	NF/S-L, 100V, 5A, 25W, >70MHz	22a	USA, Tix	MJE15029, MJE15031
2N561	Ge-P	NF/S-L, 60V, 5A, 50W	23a	USA	AL102..103, AUY21..22, 2N1546..48, ++
2N5610	Si-N	NF/S-L, 100V, 5A, 25W, >70MHz	22a	USA, Tix	MJE15028, ME15030
2N5611	Si-P	NF/S-L, 120V, 5A, 25W, >60MHz	22a	USA, Tix	MJE15029, MJE15031
2N5612	Si-N	NF/S-L, 120V, 5A, 25W, >60MHz	22a	USA, Tix	MJE15028, ME15030
2N5613	Si-P	NF/S-L, 80V, 5A, 50W, >70MHz	23a	USA	2N5621, 2SA1141, 2SA1146, 2SA1186, ++
2N5614	Si-N	NF/S-L, 80V, 5A, 50W, >70MHz	23a	USA	2N5622, 2SC2681, 2SC2706, 2SC2837, ++
2N5615	Si-P	NF/S-L, 100V, 5A, 50W, >60MHz	23a	USA	2N5623, 2SA1141, 2SA1146, 2SA1186, ++
2N5616	Si-N	NF/S-L, 100V, 5A, 50W, >60MHz	23a	USA	2N5624, 2SC2681, 2SC2706, 2SC2837, ++
2N5617	Si-P	NF/S-L, 100V, 5A, 50W, >70MHz	23a	USA	2N5625, 2SA1141, 2SA1146, 2SA1186, ++
2N5618	Si-N	NF/S-L, 100V, 5A, 50W, >70MHz	23a	USA	2N5626, 2SC2681, 2SC2706, 2SC2837, ++
2N5619	Si-P	NF/S-L, 120V, 5A, 50W, >60MHz	23a	USA	2N5627, 2SA1141, 2SA1146, 2SA1186, ++
2N5620	Si-N	NF/S-L, 120V, 5A, 50W, >60MHz	23a	USA	2N5628, 2SC2681, 2SC2706, 2SC2837, ++
2N5621	Si-P	NF/S-L, 80V, 10A, 100W, >40MHz	23a	USA	2SA1146, 2SA1186, 2SA1227, 2SSA1386
2N5622	Si-N	NF/S-L, 80V, 10A, 100W, >40MHz	23a	USA	2SC2681, 2SC2706, 2SC2837, 2SSC2987
2N5623	Si-P	NF/S-L, 100V, 10A, 100W, >30MHz	23a	USA	2SA1146, 2SA1186, 2SA1227, 2SSA1386
2N5624	Si-N	NF/S-L, 100V, 10A, 100W, >30MHz	23a	USA	2SC2681, 2SC2706, 2SC2837, 2SSC2987
2N5625	Si-P	NF/S-L, 100V, 10A, 100W, >40MHz	23a	USA	2SA1146, 2SA1186, 2SA1227, 2SSA1386
2N5626	Si-N	NF/S-L, 100V, 10A, 100W, >40MHz	23a	USA	2SC2681, 2SC2706, 2SC2837, 2SSC2987
2N5627	Si-P	NF/S-L, 120V, 10A, 100W, >30MHz	23a	USA	2SA1146, 2SA1186, 2SA1227, 2SSA1386
2N5628	Si-N	NF/S-L, 120V, 10A, 100W, >30MHz	23a	USA	2SC2681, 2SC2706, 2SC2837, 2SSC2987
2N5629	Si-N	NF/S-L, 100V, 16A, 200W, >1MHz	23a	USA, Mot, Rca	BD317, BDX50, 2N3773, 2SC2608
2N5629	Si-N			Sgs, Tix	—
2N563	Ge-P	NF/S, 30V, 0,3A, 0,15W, β=25	1a	USA	AC128, AC152..153, AC188
2N5630	Si-N	=2N5629: 120V	23a		BDX50, 2N3773, MJ15015, 2SC2608
2N5631	Si-N	=2N5629: 140V	23a		BDX50, 2N3773, MJ15015, 2SC2608
2N5632	Si-N	NF/S-L, 100V, 10A, 150W, >1MHz	23a	USA, Mot, Rca	BD317, BDX50, 2N3773, 2SC2608
2N5632	Si-N			Tix	—
2N5633	Si-N	=2N5632: 120V	23a		BDX50, 2N3773, MJ15015, 2SC2608
2N5634	Si-N	=2N5632: 140V	23a		BDX50, MJ15015, 2N3773, 2SC2608
2N5635	Si-N	UHF-L, 60V, 1A, PQ=3,2W(400MHz)	55r	Mot, Tho	BLW93
2N5636	Si-N	UHF-L, 60V, 1,5A, PQ=8,4W(400MHz)	55r	Mot, Tho	BLW91, 2SC2693
2N5637	Si-N	UHF-L, 60V, 3A, PQ=22W(400MHz)	55r	Mot, Tho	BLX95, 2SC2694
2N5638	N-FET	S, Chopper, 30V, Idss>50mA, <9/15ns	7d	USA, Mot, Mic	BFS74, BFS77, BSV78, 2N4856, 2N4859++
2N5639	N-FET	S, Chopper, 30V, Idss>25mA, <14/30ns	7d	USA, Mot, Mic	BFS75, BFS78, BSV79, 2N4857, 2N4860++
2N564	Ge-P	=2N563: 0,12W	2a	USA	AC128, AC152..153, AC188
2N5640	N-FET	S, Chopper, 30V, Idss>5mA, <18/45ns	7d	USA, Mot, Mic	BFS76, BFS79, BSV80, 2N4858, 2N4861++

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2N5641	Si-N	VHF-L, 65V, 1A, PQ=7W(175MHz)	55r	Mot, Tho, Tix	BLY 98
2N5642	Si-N	VHF-L, 65V, 3A, PQ=20W(175MHz)	55r	Mot, Tho, Tix	2SC2888
2N5643	Si-N	VHF-L, 65V, 5A, PQ=40W(175MHz)	55r	Mot, Tho, Tix	BLW25, 2SC2889
2N5644	Si-N	UHF-Tr/E, 36V, 0,25A, PQ=1W(470MHz)	55r	Mot, Tix	2N5944
2N5645	Si-N	UHF-Tr/E, 36V, 1A, PQ=4W(470MHz)	55r	Mot, Tix	BLW43, BLW80
2N5646	Si-N	UHF-Tr/E, 36V, 2A, PQ=12W(470MHz)	55r	Mot, Tix	BLW44, 2N5946
2N5647	N-FET	Uni, ra, 50V, Idss>0,3mA, Up<1,8V	5k	Sol	2N4336, 2SK118
2N5648	N-FET	Uni, ra, 50V, Idss>0,5mA, Up<2,4V	5k	Sol	2N4339, 2N5358, 2SK83, 2SK193, 195
2N5649	N-FET	Uni, ra, 50V, Idss>0,8mA, Up<3V	5k	Sol	2N4339, 2N5358, 2SK83, 2SK193, 195
2N565	Ge-P	NF/S, 30V, 0,3A, 0,15W, β=55	1a	USA	AC126+F14834, AC152..153, AC188
2N5650	Si-N	UHF, 20V, 0,03A, 0,15W, >2GHz	5g	Nip, Six	BFR15, BFS55, BFT88..67
2N5651	Si-N	UHF, 20V, 0,03A, 0,15W, >2GHz	5g	Nip, Six	BFR15, BFS55, BFT88..67
2N5652	Si-N	UHF, 20V, 0,03A, 0,15W, >2GHz	5g		BFR15, BFS55, BFT66..67
2N5653	N-FET	S, Chopper, Idss>40mA, <9/15ns	7d	USA, Mot, Mic	BFS74, BFS77, BSV78, 2N4856, 2N4859
2N5654	N-FET	S, Chopper, Idss>15mA, <14/30ns	7d	USA, Mot, Mic	BFS75, BFS78, BSV79, 2N4857, 2N4860
2N5655	Si-N	NF/S/Vid-L, 275V, 0,5A, 20W, >10MHz	14h	Mot, Nsc, Sgs	BF666, BF756..759, (BF461..462)
2N5656	Si-N	=2N5655: 325V	14h		BF759, (BF462)
2N5657	Si-N	=2N5655: 375V	14h		BD410, 2SC2899, 2SC3051, 2SC3425
2N5658	Si-N	S-L, 120/60V, 10A, 30W, >30MHz	49m	USA	(2N5288..89, 2N5542)
2N5659	Si-N	=2N5659: Iso	49a		(2N5286..89, 2N5542)
2N566	Ge-P	=2N565: 0,12W	2a	USA	AC128, AC152..153, AC188
2N5660	Si-N	NF/S-L, 250/200V, 1A, 35W, >20MHz	22a	USA	BUW40(A,B), TIP47..50, 2N3738..39, ++
2N5661	Si-N	=2N5660: 400/300V	22a		BUW40(A,B), TIP47..50, 2N4298..99, ++
2N5662	Si-N	=2N5660: 15W(Tc=100°)	2a		BSS46..49, BUX51..54, 2N3439..40
2N5663	Si-N	=2N5660: 400/300V, 15W(Tc=100°)	2a		BSS49, BUX54, 2N3439
2N5664	Si-N	NF/S-L, 250/200V, 3A, 52,5W, >20MHz	22a	USA, Tix	BUY63..64, TIP75(A..C), 2SC2929, ++
2N5665	Si-N	=2N5664: 400/300V	22a		BUY63..64, TIP75A..C, 2SC2929, ++
2N5666	Si-N	=2N5664: 15W(Tc=100°)	2a		BUX51..54, 2SD625
2N5667	Si-N	=2N5664: 400/300V, 15W(Tc=100°)	2a		BUX54
2N5668	N-FET	VHF, 25V, Idss>1mA, Up<4V	7d	Mic, Mot, Nsc	2N5246, 2SK107, 2SK161
2N5669	N-FET	VHF, 25V, Idss>4mA, Up<6V	7d	Mic, Mot, Nsc	BFS60, BFW11, 2N4416, 2N5245, 2N5396
2N567	Ge-P	NF/S, 30V, 0,3A, 0,15W, β=100	1a	USA	AC128, AC152..153, AC166
2N5670	N-FET	VHF, 25V, Idss>8mA, Up<8V	7d	Mic, Mot, Nsc	BF244C..245C, BFW10
2N5671	Si-N	NF/S-L, 120/90V, 30A, 140W, >50MHz	23a	USA, Sgs, Tix	(BDW30, BDW32, BDY58)
2N5672	Si-N	=2N5671: 150/120V	23a		(BDW32, BDY58)
2N5675	Si-P	NF/S, 125/100V, 2A, 1W, >50MHz	2a	Ssi, Stc, Tra	—
2N5676	Si-P	=2N5675:	22a		2SA1078..79, 2SA1133, 2SB719..720
2N5677	Si-P	S-L, 125/100V, 10A, 50W(Tc=100°)	49m	USA	2N5290..91
2N5678	Si-P	S-L, 125/100V, 20A, 100W(Tc=100°)	49m		—
2N5679	Si-P	NF/S, 100V, 1A, 1W, >30MHz	2a	USA, Mot, Sgs	BCX60, BSS17, 2N3634..35, 2N5322
2N5679	Si-P			Fch, Phi, Tix	—
2N568	Ge-P	=2N567: 0,12W	2a	USA	AC128, AC152..153, AC188
2N5680	Si-P	=2N5679: 120V	2a		2N3634..35
2N5881	Si-N	NF/S, 100V, 1A, 1W, >30MHz	2a	USA, Mot, Sgs	BCX40, 2N3019..20, 2N4300, 2SC1860
2N5681	Si-N			Fch, Tix	—
2N5682	Si-N	=2N5681: 120V	2a		2N3019..20, 2SC1860
2N5683	Si-P	NF/S-L, 60V, 50A, 300W, >2MHz	23a	USA, Mot, Tix	2N6377..79
2N5884	Si-P	=2N5663: 60V	23a		2N6377..79
2N5685	Si-N	NF/S-L, 60V, 50A, 300W, >2MHz	23a	USA, Mot, Tix	2N5575..80
2N5686	Si-N	=2N5665: 60V	23a		2N5576..60
2N5687	Si-N	HF-Tr/E, 40V, 0,5A, 5W(Tc=25°)	2a	Tix, Trw	—
2N5688	Si-N	HF-L, 40V, 0,5A, 10W	55r	Tix, Trw	—
2N5669	Si-N	HF-L, 60V, 3A, 25W	55r	Tix, Trw	—
2N569	Ge-P	NF/S, 30V, 0,3A, 0,15W, β=150	1a	USA	AC126, AC152..153, AC168
2N5690	Si-N	HF-L, 50V, 5A, 50W	55r	Tix, Trw	—
2N5691	Si-N	HF-L, 50V, 8A, 88W	59r	Tix, Trw	—
2N5692	Ge-P	S-L, 50V, 40A, 120W	23a	Gpd, Mot	2N2357..59, 2N5435..40
2N5693	Ge-P	=2N5692: 80V	23a		2N2358..59, 2N5435..40
2N5694	Ge-P	=2N5692: 100V	23a		2N2358..59, 2N5436..37, 2N5439..40
2N5695	Ge-P	=2N5692: 120V	23a		2N2359, 2N5437, 2N5440
2N5698	Ge-P	=2N5692: 140V	23a		2N5437, 2N5440
2N5697	Si-N	HF-Tr/E, 40V, 0,5A, 3,5W(Tc=25°)	2a	Tix, Trw	—
2N5698	Si-N	HF-Tr/E, 40V, 0,5A, 5W	51r	Tix, Trw	—
2N5699	Si-N	HF-L, 40V, 1A, 10W	55r	Tix, Trw	—
2N57	Ge-P	NF/S-L, 60V, 0,8A, 20W		Sol	—
2N570	Ge-P	=2N569: 0,12W	2a	USA	AC126, AC152..153, AC188

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2N5700	Si-N	HF-L, 40V, 3A, 35W	55r	Trw	—
2N5701	Si-N	HF-L, 40V, 3A, 35W	55r	Trw	—
2N5702	Si-N	HF-Tr/E, 36V, 0,5A, 0,88W	2a	Tix,Trw	—
2N5703	Si-N	HF-Tr/E, 36V, 0,75A, 10W	55r	Tix,Trw	—
2N5704	Si-N	HF-L, 36V, 2A, 25W	55r	Tix,Trw	—
2N5705	Si-N	HF-L, 36V, 4A, 44W	55r	Tix,Trw	—
2N5706	Si-N	HF-L, 36V, 7A, 80W	59r	Tix,Trw	—
2N5707	Si-N	HF-L, 70V, 4A, PQ>20W(30MHz)	55r	Tix,Trw	MRF401, MRF449A
2N5706	Si-N	HF-L, 70V, 6A, PQ>20W(28MHz)	55r	Tix,Trw	MRF449A
2N5709	Si-N	HF-L, 70V, 12A, PQ>40W(28MHz)	59r	Tix,Trw	2SC1764
2N571+A14890	Ge-P	NF/S, 30V, 0,3A, 0,15W, β=200	1a	USA	AC128, AC152..153, AC188
2N5710	Si-N	HF-Tr/E, 40V, 0,5A, 3,5W(Tc=25°)	2a	Tix,Trw	—
2N5711	Si-N	HF-Tr/E, 60V, 0,75A, 10W	55r	Tix,Trw	—
2N5712	Si-N	HF-L, 60V, 2A, 25W	55r	Tix,Trw	—
2N5713	Si-N	HF-L, 60V, 5A, 45W	55r	Tix,Trw	—
2N5714	Si-N	HF-L, 60V, 8A, 70W	60c	Trw	—
2N5715	Si-N	UHF-A/Tr, 50V, 0,2A, 6W(Tc=25°), >3,5GHz	2a	Trw	—
2N5716	N-FET	NF, ra, 40V, Idss>0,05mA, Up<3V	7d	Mic,Mot,Nsc	2N3367, 2N3370, 2N4118
2N5717	N-FET	NF, ra, 40V, Idss>0,2mA, Up<5V	7d	Mic,Mot,Nsc	2N3366, 2N4119
2N5718	N-FET	NF, ra, 40V, Idss>0,8mA, Up<8V	7d	Mic,Mot,Nsc	2N3365
2N5719	50Hz-Thy	60V, 0,2A(Tc=90°), Igt/Ih<0,02/<2mA	2a	Tag,Uni	(2N2324A)
2N572	Ge-P	=2N571: 0,12W	2a	U8A	AC128, AC152..153, AC188
2N5720	50Hz-Thy	=2N5719: 100V	2a		(2N2324A)
2N5721	50Hz-Thy	=2N5719: 200V	2a		(2N2326A)
2N5722	50Hz-Thy	=2N5719: 300V	2a		(2N2328A)
2N5723	50Hz-Thy	=2N5719: 400V	2a		(2N2329A)
2N5724	50Hz-Thy	=2N5719: 0,39A(Tc=90°)	2a		(2N2324A)
2N5725	50Hz-Thy	=2N5720: 0,39A(Tc=90°)	2a		(2N2324A)
2N5726	50Hz-Thy	=2N5721: 0,39A(Tc=90°)	2a		(2N2326A)
2N5727	50Hz-Thy	=2N5722: 0,39A(Tc=90°)	2a		(2N2326A)
2N5728	50Hz-Thy	=2N5723: 0,39A(Tc=90°)	2a		(2N2329A)
2N5729	Si-N	S-L, 100/80V, 5A, 11,7W(Tc=25°), >30MHz	2a	Sol,Ssi,Stc	2N4895..97, 2N5336..39, BUX34, BUY80
2N573	Ge-P	NF/S, 40V, 0,25A, 0,2W	2a	U8A	2N1191..94, 2SB56A
2N5730	Si-N	S-L, 100/60V, 10A, 45W, >30MHz	49a		(2N5288..89)
2N5731	Si-N	S-L, 100/60V, 20A, 75W, >30MHz	49a	Sol,Sei,Stc	—
2N5732	Si-N	S-L, 100/80V, 20A, 87,5W, >30MHz	23a		(BDX40, BDY57, 2N3772)
2N5733	Si-N	S-L, 100/80V, 30A, 150W, >30MHz	49a	Sol,Ssi,Stc	—
2N5734	Si-N	S-L, 100/80V, 30A, 125W, >30MHz	23a		(BDY29, MJ802, 2SD797)
2N5735	Si-N	SMD, 60V, 0,3A, 0,36W, >200MHz	Chip	Amp	—
2N5736	Si-N	SMD, 60V, 0,3A, 0,36W, >200MHz	Chip	Amp	—
2N5737	Si-P	NF/S-L, 80V, 10A, 50W(Tc=100°), >10MHz	23a	USA	BD312, BD546A, BDW22A, 2N5875..76, ++
2N5736	Si-P	=2N5737: 100V	23a		BD318, BD546C, BDW22C, 2N8229..31, ++
2N5739	Si-P	=2N5737: 20W(Tc=100°)	22a		BD706, BD744A, BD608, BDT82, ++
2N574	Ge-P	NF/S-L, 60V, 10A, 187W	≈49m	Gpd,Sem	—
2N5740	Si-P	=2N5737: 100V, 20W(Tc=100°)	22a		BD712, BD744C, BDT88, ++
2N5741	Si-P	NF/S-L, 60V, 20A, 65W(Tc=100°), >10MHz	23a	USA	BD250A, BD367, BD746A, 2N5883..84, ++
2N5742	Si-P	=2N5741: 100V	23a		BD250C, BD746C, MJ4502
2N5743	Si-P	=2N5741: 25W(Tc=100°)	22a		—
2N5744	Si-P	=2N5741: 100V, 25W(Tc=100°)	22a		—
2N5745	Si-P	NF/S-L, 80V, 20A, 200W, >2MHz	23a	USA,Mot,Sgs	BD369, MJ4502, 2N5884
2N574A	Ge-P	=2N574: 60V	≈49m		—
2N575	Ge-P	NF/S-L, 60V, 25A, 187W	≈49m	Gpd,Sem	—
2N5754	Triac	=T2303A	2m	Rca,Tag	→T2303A
2N5755	Triec	=T2303B	2m		→T2303B
2N5756	Triac	=T2303D	2m		→T2303D
2N5757	Triec	=T2303M	2m		→T2303M
2N5758	Si-N	NF/S-L, 100V, 6A, 150W, >1MHz	23a	USA, Mot, Tix	BD245C, BDV95, BDX95, 2N5832..33, ++
2N5759	Si-N	=2N5758: 120V	23a		BD245D, 2N4348, 2N5834, 2SC2607..06, ++
2N575A	Ge-P	=2N575: 60V	≈49m		—
2N576	Ge-N	NF/S, 20V, 0,4A, 0,2W, 5MHz	2a(B=case)	U8A	—
2N5760	Si-N	=2N5758: 140V	23a		BD245D, 2N4348, 2N5834, 2SC2607..08, ++
2N5761	Si-N	UHF, 20V, 0,03A, 0,25W, >3,7GHz	51e	Nip	BFQ60, BFQ71, 2SC1119, 2SC1336, ++
2N5762	Si-N	UHF, 20V, 0,04A, 0,3W, >3,3GHz	51s	Nip	BFQ60, BFQ71, 2SC1119, 2SC1336, ++
2N5763	Si-P	S, RadH, 65V, 0,8A, 0,4W, <50/250ns	2a	Mot	—
2N5764	Si-N	HF-Tr/E, 55V, 0,75A, 10W	55r	Trw	—
2N5765	Si-N	HF-L, 55V, 1,5A, 19W	55r	Trw	—

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2N5766	Si-N	HF-Tr/E, 55V, 0,2A, 5W	55r	Trw	—
2N5767	Si-N	HF-Tr/E, 55V, 0,35A, 10W	55r	Trw	—
2N5768	Si-N	HF-Tr/E, 55V, 0,7A, 20W	55r	Trw	—
2N5769	Si-N	S, 40V, 0,2A, 0,625W, >500MHz, <12/18ns	7e	USA,Mic,Nsc	BSS10..11, BSX19..20, 2N2368..69(A),++
2N576A	Ge-N	=2N576: 40V, 8MHz	2a(B=case)		—
2N577	Opto				—
2N5770	Si-N	UHF, 30V, 0,05A, 0,7W, >900MHz	7e	USA,Nsc	BF377..378, BF689, BF763, 2N2857,++
2N5771	Si-P	S, 15V, 0,05A, 0,625W, >850MHz, <15/20ns	7e	USA,Mot,Nsc	BSX36, 2N4313, 2N5056..57
2N5772	Si-N	S, 40V, 0,2A, 0,625W, >350MHz, <25/35ns	7e	USA,Min,Nsc	BSS10..11, BSX19..20, 2N2368..89(A),++
2N5773	Si-N	HF-Tr/E, 85V, 0,5A, 5W	55r	Trw	—
2N5774	Si-N	HF-L, 65V, 1,5A, 18W	55r	Trw	—
2N5775	Si-N	HF-L, 65V, 3A, 40W	60c	Trw	—
2N5776	Si-N	HF-L, 85V, 6A, 70W	60c	Trw	—
2N5777..5780	Opto				—
2N578	Ge-P	NF/S, 20V, 0,4A, 0,12W, 5MHz	2a	USA	ASY76..77
2N5781	Si-P	NF/S, 80V, 3,5A, 1W, <500/2500ns	2a	USA,Rca	2N4236, 2N6303
2N5782	Si-P	=2N5781: 65V	2a		2N3720, 2N3668, 2N4235..36, 2N6303
2N5783	Si-P	=2N5781: 45V	2a		2N3720, 2N3868, 2N4235..36, 2N6303
2N5784	Si-N	NF/S, 80V, 3,5A, 1W, <5/15µs	2a	USA,Rca	BSX63..84, 2N4236..39, 2SC2214,++
2N5785	Si-N	=2N5784: 85V	2a		BSX62..64, 2N4236..39, 2SC2214,++
2N5788	Si-N	=2N5784: 45V	2a		BSX62..84, 2N4237..39, 2SC2214,++
2N5787	50Hz-Thy	30V, 0,24A, Igt/Ih<0,35/<10mA	8a	Fch,Mot	(2N2323, 2N6332, TAG615-100, TIC44,)++,
2N5788	50Hz-Thy	=2N5787: 60V	8a		(2N2324, 2N8334, TAG815-100, TIC46,)++
2N5789	50Hz-Thy	=2N5787: 100V	8a		(2N2324, 2N6334, TAG815-100, TIC46,)++
2N579	Ge-P	=2N578: 8MHz	2a	USA	ASY76..77
2N5790	50Hz-Thy	=2N5787: 200V	8a		(2N2326, 2N6335, TAG615-200, TIC47,)++
2N5791	50Hz-Thy	=2N5787: 300V	8a		(2N2326, 2N8336, TAG615-300, TAG06C,)+
2N5792	50Hz-Thy	=2N5767: 400V	8a		(2N2329, 2N6337, TAG615-400, TAG06D,)+
2N5793	Si-N	Dual, S, 75V, 0,6A, 0,6W, >250MHz	TO-99	Mot,Ray,Sca	2N3409..11, 2N3728..29
2N5794	Si-N	Dual, S, 75V, 0,6A, 0,6W, >250MHz	TO-77		2N3409..11, 2N3728..29
2N5795	Si-P	Dual, S, 60V, 0,6A, 0,6W, >200MHz	TO-77	Mot,Ray,Sca	BFX11, 2N4015..18
2N5766	Si-P	Dual, S, 60V, 0,6A, 0,8W, >200MHz	TO-77		BFX11, 2N4015..16
2N5797	P-FET	NF, sym, 40V, Idss>0,02mA, Up<4V	7c	Mot	2N2606
2N5798	P-FET	NF, sym, 40V, Idss>0,08mA, Up<6V	7c	Mot	—
2N5799	P-FET	NF, sym, 40V, Idss>0,25mA, Up<8V	7c	Mot	—
2N580	Ge-P	=2N578: 15MHz	2a	USA	ASY76..77
2N5600	P-FET	NF, sym, 40V, Idss>0,7mA, Up<9V	7c	Mot	—
2N5601	N-FET	Uni, ra, 40V, Idss>2mA, Up<4V	2b	Mot	2N5360, 2N5246, 2SK107
2N5602	N-FET	Uni, ra, 40V, Idss>10mA, Up<6V	2b	Mot	BF256C, BF348, BFT10, 2N5397, 2N5486
2N5603	N-FET	Uni, ra, 40V, Idss>30mA, Up<8V	2b	Mot	BFT10C, 2SK125
2N5804	Si-N	S-L, 300/225, 5A, 110W, >15MHz	23a	USA,Rca	BUW71, BUX16A..C, BUX18(A..C),++
2N5605	Si-N	=2N5804: 375/300V	23a		BUW71, BUX18B..C, BUX18B..C,++
2N5606	Triac	200V, 25A, Igt/Ih<150/<75mA	21l	Rca	BTX94/200
2N5607	Triac	=2N5606: 400V	21l		BTX94/400
2N5608	Tnac	=2N5806: 500V	21l		BTX94/500
2N5609	Triac	=2N5806: 600V	21l		BTX94/600
2N561	Ge-P	NF/S, 18V, 0,1A, 0,08W, 8MHz	2a	USA	ASY26..27, ASY76..77
2N5610	Si-N	NF-Tr, 35V, 0,75A, 0,5W, >100MHz, B>60	7a	Gen,Mic,Sem	BC337..336, BC635, BC637, BC639,++
2N5810	Si-N			Spr	—
2N5811	Si-P	NF-Tr, 35V, 0,75A, 0,5W, >100MHz, B>60	7a	Gen,Mic,Sem	BC327..328, BC636, BC639, BC640,++
2N5811	Si-P			Spr	—
2N5612	Si-N	=2N5810: >135MHz, B>150	7a		BC337..338, BC635, BC637, BC639,++
2N5613	Si-P	=2N5811: >135MHz, B>150	7a		BC327..328, BC636, BC636, BC640,++
2N5614	Si-N	=2N5810: 50V	7a		BC337, BC635, BC837, BC639,++
2N5815	Si-P	=2N5611: 50V	7a		BC327, BC636, BC636, BC840,++
2N5816	Si-N	=2N5810: 50V, >120MHz, B>100	7a		BC337, BC635, BC637, BC639,++
2N5617	Si-P	=2N5811: 50V, >120MHz, B>100	7a		BC327, BC636, BC638, BC640,++
2N5618	Si-N	=2N5810: 50V, >135MHz, B>150	7a		BC337, BC635, BC637, BC639,++
2N5619	Si-P	=2N5611: 50V, >135MHz, B>150	7a		BC327, BC636, BC636, BC840,++
2N582	Ge-P	NF/S, 25V, 0,1A, 0,12W, 18MHz	2a	USA	ASY26..27, ASY76..77
2N5620	Si-N	=2N5810: 70V	7a		BC639, 2SD667, 2SD1226, 2SD1766,++
2N5621	Si-P	=2N5611: 70V	7a		BC840, 2B647, 2SB910, 2SB1041,++
2N5622	Si-N	=2N5610: 70V, >120MHz, B>100	7a		BC639, 2SD667, 26D1226, 2SD1766,++
2N5823	Si-P	=2N5611: 70V, >120MHz, B>100	7a		BC840, 2B647, 2SB910, 2SB1041,++
2N5824	Si-N	Uni, 50V, 0,1A, 0,36W, >90MHz, B>60	7a	USA,Gen,Mic	BC187, BC162, BC237, BC547,++
2N5625	Si-N	=2N5824: B>100	7a		BC187, BC162, BC237, BC547,++

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2N5826	Si-N	=2N5824: B>150	7a		BC167, BC182, BC237, BC547, ++
2N5827	Si-N	=2N5824: B>250	7a		BC167, BC182, BC237, BC547, ++
2N5827A	Si-N	=2N5827: ra	7a		BC414, BC550, 2SC1775(A), 2SC2390, ++
2N5828	Si-N	=2N5824: B>400	7a		BC167, BC182, BC237, BC547, ++
2N5828A	Si-N	=2N5828: ra	7a		BC414, BC550, 2SC1775(A), 2SC2390, ++
2N5829	Si-P	UHF, ra, 30V, 0,03A, 0,2W, 1,5GHz	5g	Mot, Sca, Tho	BF316, BF439, BF516, BF606, BFR38++
2N583	Ge-P	NF/S, 18V, 0,1A, 0,08W, 8MHz	2a	USA	ASY26..27, ASY76..77
2N5830	Si-N	S/Vid, 120V, 0,6A, 0,625W, >100MHz	7e	Fch, Nsc, Spr	BF391..393, BFP22, MPS-A4243
2N5831	Si-N	=2N5830: 160V	7e		BF391..393, BFP22, MPS-A42..43
2N5832	Si-N	=2N5830: 160V	7e		BF391..393, BFP22, MPS-A42..43
2N5833	Si-N	=2N5830: 200V	7e		BF391..393, BFP22, MPS-A42..43
2N5834	Si-P	VHF-Tr/E, 60V, 1A, PQ=2,5W(175MHz)	2	Mot, Tix	—
2N5835	Si-N	SS/UHF, 15V, 15mA, 0,2W, >2,5GHz	5g	Mot, Sca	BFR15, BFW99, BFT66..67
2N5836	Si-N	SS/UHF, 15V, 0,2A, >2GHz	2a	Mot, Sca	(BFR95)
2N5837	Si-N	SS/UHF, 10V, 0,3A, >1,7GHz	2a	Mot, Sca	(2SC1253, 2SC1366, 2SC1952)
2N5838	Si-N	S-L, 275/250V, 3A, 100W, >5MHz	23a	USA, Mot, Tix	BU606..608, BUX16A..C, BUW71, ++
2N5839	Si-N	=2N5838: 300/275V	23a		BU608..608, BUX16B..C, BUW71, ++
2N584	Ge-P	NF/S, 25V, 0,1A, 0,12W, 18MHz	2a	USA	ASY26..27, ASY76..77
2N5840	Si-N	=2N5838: 375/350V	23a		BU608..606, BUX16B..C, BUW71, ++
2N5841	Si-N	SS/UHF, 20V, 0,1A, 0,35W, >2,7GHz	5g	Mot, Sca	2SC3337, (BFR95)
2N5842	Si-N	SS/UHF, 20V, 0,1A, 0,35W, >2GHz	5g		2SC3337, (BFR95)
2N5843	Si-P	Dual, ra, 50V, 0,05A, 0,6W, >200MHz	TO-7	Fch, Mot	BFX11, 2N4015..16
2N5844	Si-P	Dual, ra, 50V, 0,05A, 0,6W, >250MHz	TO-7		BFX11, 2N4015..16
2N5845	Si-N	S, 50V, 1A, 0,825W, <45/70ns	7e	Mot, Spr	2N3738..37, 2N4013..14
2N5845A	Si-N	=2N5845: <40/65ns	7e		2N3738..37, 2N4013..14
2N5846	Si-N	HF-L, 38V, 1A, PQ>3,5W(50MHz)	49a	Mot	—
2N5847	Si-N	HF-L, 38V, 2A, PQ>8W(50MHz)	49a	Mot	—
2N5848	Si-N	HF-L, 48V, 3,5A, PQ>20W(50MHz)	55r	Mot	MRF234
2N5349	Si-N	HF-L, 48V, 7A, PQ>40W(50MHz)	55r	Mot, Tho	—
2N535	Ge-N	NF/S, 25V, 0,2A, 0,12W, 5MHz	2a	USA	ASY28..29, ASY73..75
2N5851	Si-N	SS/UHF, 30V, 0,1A, 0,5W, 1,6/1,6ns	5g	Mot, Sca, Ssi	—
2N5852	Si-N	SS/UHF, 30V, 0,1A, 0,5W, 1,6/1,6ns	5g	Mot, Sca, Ssi	—
2N5853	Si-P	S-L, 100V, 10A, 86W(Tc=100°), >15MHz	49a	USA	2N5290..91
2N5854	Si-N	S-L, 100V, 10A, 66W(Tc=100°), >20MHz	49a		2N5288..89
2N5855	Si-P	Uni, 60V, 1A, 0,75W, >100MHz	8a	Fch	BC327A, BC838, BC640, 2SB647, ++
2N5858	Si-N	Uni, 60V, 1A, 0,75W, >100MHz	8a	Fch	BC337A, BC637, BC639, 2SB647, ++
2N5857	Si-P	=2N5855: 60V	8a		BC640, 2SB647, 2SB910, 2SB1041, ++
2N5858	Si-N	=2N5856: 80V	8a		BC639, 2SD667, 2SD1226, 2SD1768, ++
2N5859	Si-N	S, 60V, 2A, 1W, >250MHz, <36/70ns	2a	Mot, Sca, Ssi	BSS14, 2N5262
2N586	Ge-P	NF/S, 45V, 0,25A, 0,25W	1a	USA	ASY76..77, 2N1191..94
2N5860	Si-N	S, 90V, 2A, 1W, >250MHz, <26/70ns	2a	Sca, Ssi	—
2N5861	Si-N	S, 100V, 2A, 1W, >200MHz, <26/70ns	2a	Mot, Sca, Ssi	—
2N5862	Si-N	VHF-L, 65V, 8A, PQ=90W(150MHz)	55r	Mot, Tix	—
2N5864	Si-P	Uni, 90V, 1,5A, 1,25W, <130/750ns	2a	USA, Mot	BCX60, BSS17, BSV17, 2N5322
2N5865	Si-P	Uni, 70V, 1A, 1,25W, <120/500ns	2a	USA, Mot	BCX60, BSS17, BSX59..61, 2N3444, ++
2N5867	Si-P	NF/S-L, 60V, 5A, 87,5W, >4MHz	23a	USA, Mot, Tix	BD246A, BDV92, BDX92, 2N5871..72, ++
2N5868	Si-P	=2N5867: 60V	23a		BD246B, BDV94, BDX94, 2N5872, ++
2N5869	Si-N	NF/S-L, 60V, 5A, 87,5W, >4MHz	23a	USA, Mot, Tix	BD245A, BDV91, BDX91, 2N5873..74, ++
2N587	Ge-N	NF/S, 40/20/40V, 0,2A, 0,15W	2a(B=case)	USA	—
2N5870	Si-N	=2N5869: 60V	23a		BD245B, BDV93, BDX93, 2N5874, ++
2N5871	Si-P	NF/S-L, 60V, 7A, 115W, >4MHz	23a	USA, Mot, Sgs	BD312, BD548A, BDW22A, 2N5875..76, ++
2N5871	Si-P			Rca, Tix	—
2N5872	Si-P	=2N5871: 60V	23a		BD314, BD546B, BDW22B, 2N5876, ++
2N5873	Si-N	NF/S-L, 60V, 7A, 115W, >4MHz	23a	USA, Mot, Sgs	BD545A, BD311, BDW21A, 2N5877..78, ++
2N5873	Si-N			Rca, Tix	—
2N5874	Si-N	=2N5873: 60V	23a		BD545A, BD313, BDW21B, 2N5878, ++
2N5875	Si-P	NF/S-L, 60V, 10A, 150W, >4MHz	23a	USA, Mot, Sgs	BD312, BD546A, BDW22A, 2N5879..60, ++
2N5875	Si-P			Rca, Tix	—
2N5876	Si-P	=2N5875: 80V	23a		BD314, BD546B, BDW22B, 2N5880, ++
2N5877	Si-N	NF/S-L, 60V, 10A, 150W, >4MHz	23a	USA, Mot, Sgs	BD311, BD545A, BDW21A, 2N5861..82, ++
2N5877	Si-N			Rca, Tix	—
2N5878	Si-N	=2N5877: 60V	23a		BD313, BD545B, BDW21B, 2N5882, ++
2N5879	Si-P	NF/S-L, 60V, 15A, 160W, >4MHz	23a	USA, Mot, Rca	BD316, BD746A, BDW52A, 2N6029..31, ++
2N5879	Si-P			Tix	—
2N588(A)	Ge-P	HF, 15V, 0,05A, 250MHz	2a	USA	AF106, AF109R, AF306
2N5880	Si-P	=2N5879: 80V	23a		BD316, BD748B, BDW52B, 2N6029..31, ++

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2N5881	Si-N	NF/S-L, 60V, 15A, 160W, >4MHz	23a	USA,Mot,Rca	BD315, BD745A, BDW51A, 2N5620..31,++
2N5881	Si-N			Tix	—
2N5882	Si-N	=2N5881: 80V	23a		BD315, BD745B, BDW51B, 2N5620..31,++
2N5883	Si-P	NF/S-L, 60V, 25A, 200W, >4MHz	23a	USA,Mot,Sgs	BD367, BD369, MJ4502, 2N4399
2N5883	Si-P			Rca,Tix	—
2N5884	Si-P	=2N5883: 80V	23a		BD369, MJ4502
2N5885	Si-N	NF/S-L, 60V, 25A, 200W, >4MHz	23a	USA, Mot, Sgs	BD388, BD368, BDY29, MJ802,++
2N5885	Si-N			Rca,Tix	—
2N5886	Si-N	=2N5885: 80V	23a		BD368, BDY29, MJ802, 2SD797,++
2N5887	Ge-P	NF/S-L, 20V, 7A, 57W, B>15	22a	Gpd,Mot,Stc	—
2N5888	Ge-P	=2N5887: 30V	22a		—
2N5889	Ge-P	=2N5887: 30V, B>30	22a		—
2N589	Ge-P	S-L, 100V, 3A, 90W	23a	USA	AL102..103, AUY34, 2N1547..48,++
2N5890	Ge-P	=2N5887: 45V, B>30	22a		—
2N5891	Ge-P	=2N5887: 60V, B>30	22a		—
2N5892	Ge-P	=2N5887: 75V, B>30	22a		—
2N5893	Ge-P	=2N5887: 30V, B>60	22a		—
2N5894	Ge-P	=2N5887: 45V, B>60	22a		—
2N5895	Ge-P	=2N5887: 60V, B>60	22a		—
2N5896	Ge-P	=2N5887: 75V, B>60	22a		—
2N589+A151277	Ge-P	=2N5887: 30V, B>100	22a		—
2N5896	Ge-P	=2N5887: 45V, B>100	22a		—
2N5899	Ge-P	=2N5887: 80V, B>100	22a		—
2N59	Ge-P	NF, 25V, 0,2A, 0,18W, B=90	2a	USA	AC125..126, AC151, ASY26..27
2N5900	Ge-P	=2N5887: 75V, B>100	22a		—
2N5901	Ge-P	=2N5887: 30V, B>175	22a		—
2N5902	N-FET	Dual, ra, 40V, Idss>0,03mA, Up<4,5V	TO-99	Isi,Nsc,Six	—
2N5902	N-FET			Sol	—
2N5903	N-FET	Dual, ra, 40V, Idss>0,03mA, Up<4,5V	TO-99		—
2N5904	N-FET	Dual, ra, 40V, Idss>0,03mA, Up<4,5V	TO-99		—
2N5905	N-FET	Dual, ra, 40V, Idss>0,03mA, Up<4,5V	TO-99		—
2N5906	N-FET	Dual, ra, 40V, Idss>0,03mA, Up<4,5V	TO-99		—
2N5907	N-FET	Dual, ra, 40V, Idss>0,03mA, Up<4,5V	TO-99		—
2N5908	N-FET	Dual, ra, 40V, Idss>0,03mA, Up<4,5V	TO-99		—
2N5909	N-FET	Dual, ra, 40V, Idss>0,03mA, Up<4,5V	TO-99		—
2N591 (/5)	Ge-P	NF/S, 32V, 0,04A, 0,05W	2a	USA	AC125..126, AC151, 2SB54, 2SB56
2N5910	Si-P	S, 20V, 0,05A, 0,31W, <25/30ns	8a	Fch,Mic,Nsc	BSX36
2N5911	N-FET	Dual, ra, 25V, Idss>7mA, Up<5V	TO-99	Isi,Nsc,Six	—
2N5911	N-FET			Sol,Tsc	—
2N5912	N-FET	Dual, ra, 25V, Idss>7mA, Up<6V	TO-99		—
2N5913	Si-N	VHF/UHF-Tr/E, 36V, 0,33A, PQ=2W(470MHz)	2a	Rca	BLX85, MRF629, 2SC2782, 2SC3185
2N5914	Si-N	UHF-Tr/E, 36V, 0,5A, PQ=2,3W(470MHz)	55s	Rca	BLW79, BLX67, BLY36, 2N5945,++
2N5915	Si-N	UHF-Tr/E, 36V, 1,5A, PQ=6,5W(470MHz)	55s	Rca	BLU97, BLX68, BLY53, 2SC2105
2N5918	Si-N	UHF-Tr/E, 55V, 0,2A, PQ>2W(400MHz)	55s	Rca	BFT91, BLW89, BLY76
2N5917	Si-N	UHF-Tr/E, 55V, 0,2A, PQ>2W(400MHz)	60e	Rca	—
2N5918	Si-N	UHF-L, 80V, 0,75A, PQ>10W(400MHz)	55s	Rca	MRF321, MRF331
2N5919	Si-N	UHF-L, 65V, 4,5A, PQ>16W(400MHz)	55s	Rca	BLX95, 2N8105, 2SC2894
2N592	Ge-P	NF/S, sym, 20V, 0,125W, >0,4MHz	2a	USA	—
2N5920	Si-N	UHF-Tr/E, 50V, 0,275A, PQ>2W(2GHz)	Koax	Rca	—
2N5921	Si-N	UHF-Tr/E, 50V, 0,7A, PQ>5W(2GHz)	Koax	Rca	—
2N5922	Si-N	UHF-Tr/E, 55V, 0,425A, PQ=1W(1GHz)	55r	Mot	BLX97
2N5923	Si-N	UHF-Tr/E, 55V, 0,75A, PQ=2,5W(1GHz)	55r	Mot	2N4430
2N5924	Si-N	UHF-Tr/E, 55V, 1,5A, PQ=5W(1GHz)	55r	Mot	—
2N5925	Si-N	UHF-L, 50V, 2,5A, PQ=10W(1GHz)	55r	Mot	—
2N5926	Si-N	S-L, 150V, 50A, 350W, >5MHz	49m	USA	2N6278..81
2N5927	Si-N	S-L, 150/120V, 100A, 350W, >5MHz	49m	Sol,Ssi,Stc	2N6309..11
2N5928	Si-N	S-L, 120/120V, 100A, 350W, >5MHz	49ra	Sol,Ssi,Stc	2N6309..11
2N5929	Si-N	S-L, 80/60V, 30A, 175W, >30MHz	23a	USA	BDW30, BDY29, MJ802, 2SD797
2N593	Ge-P	NF/S, sym, 40V, 0,125W, >0,6MHz	2a	USA	—
2N5930	Si-N	=2N5929: 130/120V	23a		BDW30, BDY58, 2N5672
2N5931	Si-N	=2N5929: 170/160V	23a		BDW34, BDW36
2N5932	Si-N	S-L, 70/60V, 30A, 175W, >30MHz	23a	USA	BDW30, BDY29, MJ802, 2SD797,++
2N5933	Si-N	=2N5931: 110/100V	23a		BDW30, BDY58, 2N5672
2N5934	Si-N	=2N5931: 150/140V	23a		BDW32, BDY58, 2N5672
2N5935	Si-N	S-L, 90/80V, 30A, 175W, >30MHz	23a	USA	BDW30, BDY29, MJ802, 2SD797,++
2N5936	Si-N	=2N5935: 130/120V	23a		BDW30, BDY58, 2N5672

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2N5937	Si-N	=2N5935: 170/160V	23a		BDW34, BDW36
2N5938	Si-N	RadH, 60V, 3A, 20W(Tc=100°), >150MHz	49a	Tix	—
2N5939	Si-N	RadH, 80V, 10A, 40W(Tc=100°), >120MHz	49a	Ker, Stc, Tix	—
2N594	Ge-N	NF/S, sym, 40V, 0,1W, >1,5MHz	2a	Ssi, Tix	—
2N5940	Si-N	=2N5939: RadH, 70V	49a		—
2N5941(T)	Si-N	AM-L, 65V, 6A, PEP=40W(30MHz)	59r	Mot, Tix	—
2N5942	Si-N	AM-L, 65V, 12A, PEP=80W(30MHz)	59r	Mot, Tho, Tix	MRF463..464
2N5943	Si-N	UHF-A/Tr, 40V, 0,4A, 1W, 1550MHz	2a	Mot, Tho	BFS50, MRF629, 2N3948, 2SC2852, ++
2N5944	Si-N	UHF-Tr/E, 38V, 0,4A, PQ=2W(470MHz)	55r	Mot, Tho, Trw	BLW79
2N5945	Si-N	UHF-L, 38V, 0,8A, PQ=4W(470MHz)	55r	Mot, Tho, Trw	BLU97, BLW43, BLW80
2N5946	Si-N	UHF-L, 38V, 2A, PQ=10W(470MHz)	55r	Mot, Tho, Trw	BLW81, 29C2106
2N5947	Si-N	VHF/UHF-A/Tr, 40V, 0,4A, 5W, 1,5GHz	55r	Mot	BFT91, BLW89, MRF313
2N5949	N-FET	Uni, ra, 30V, Idss>12mA, Up<7V	7b	Nsc, Tix, Tsc	BF244C. F15214245C, BF256C, BFT10A, ++
2N595	Ge-N	NF/S, sym, 15V, 0,1W, >3MHz	2a	Ssi, Tix	—
2N5950	N-FET	Uni, ra, 30V, Idss>10mA, Up<6V	7b	Nsc, Tix, Tsc	BF256C, BF348, BFT10A, 2N5397, 2N5486
2N5951	N-FET	Uni, ra, 30V, Idss>7mA, Up<5V	7b	Nsc, Tix, Tsc	BF259B
2N5952	N-FET	Uni, ra, 30V, Idss>4mA, Up<3,5V	7b	Nsc, Tix, Tsc	BC264, BF410C, 2N5485, 2SK147, 29K168
2N5953	N-FET	Uni, ra, 30V, Idss>2,5mA, Up<3V	7b	Nsc, Tix, Tsc	BC264, BF410B, 2SK192, 2SK370
2N5954	Si-P	NF/S-L, 90V, 6A, 40W, >5MHz	22a	Rca, Stc, Tra	BD244C, BD544C, BD802, 2N6318, ++
2N5955	Si-P	=2N5954: 70V	22a		BD244B, BD544B, BD800, 2N6318, ++
2N5959	Si-P	=2N5954: 50V	22a		BD244A, BD544A, BD798, 2N6317, ++
2N5957	Si-N	S-L, 100V, 20A, 150W, >10MHz	49m	USA	—
2N5958	Si-P	S-L, 100V, 20A, 150W, >10MHz	49m	USA	—
2N5959	Si-N	=2N5957: Iso	49a		—
2N596	Ge-N	NF/S, sym, 10V, 0,1W, >5MHz	2a	Ssi, Tix	—
2N5960	Si-P	=2N5958: Iso	49a		—
2N5961	Si-N	Uni, ra, 80V, 0,05A, 0,625W, B>150	7e	Fch, Nsc	BC174, BC162, BC190, BC546, ++
2N5962	Si-N	=2N5961: 45V, B>800	7s	Fch, Nsc	29C3495
2N5963	Si-N	=2N5961: 30V, B>1200	7e	Fch	29C3495
2N5964	Si-N	Vid, 180V, 0,6A, 0,7W, >100MHz	2a	Fch	BF391..393, BFP22, MPS-A43, 29D624, ++
2N5965	Si-N	=2N5964: 200V	2a	Fch	BF391..393, BFP22, MPS-A43, 29D624, ++
2N5966	Si-N	S-L, 100/100V, 30A, 187W, >10MHz	49m	U6A	2N2824..25
2N5967	Si-P	S-L, 100/100V, 30A, 167W, >10MHz	49m	U6A	—
2N5966	Si-N	=2N5966: Iso	49a		—
2N5969	Si-P	=2N5967: Iso	49a		—
2N597	Ge-P	NF/S, 45/40/45V, 0,5A, 0,25W, >3MHz	2a	USA	(ASY76..77)
2N5970	Si-N	S-L, 80/60V, 15A, 150W, >4MHz, B>20	23a	USA	BD315, BD545B, 2N3772, 2N5829..31, ++
2N5971	Si-N	=2N5970: B>50	23a		BD315, BD545B, 2N3772, 2N5629..31, ++
2N5972	Si-N	=2N5970: 100/80V	23a		BDS17, BD545C, 2N3772, 2N5629..31, ++
2N5973	Si-N	=2N5970: 120/100V	23a		BDX50, BD545D, 2N3773, 2N5630..S1, ++
2N5974	Si-P	NF/S-L, 80V, 5A, 75W, >2MHz	16h	Mot	BD200, 2N5980, 2SB579
2N5975	Si-P	=2N5974: 80V	16h		2N5981, 2SB580
2N5976	Si-P	=2N5974: 100V	16h		2N5982, 2SB581
2N5977	Si-N	NF/S-L, 80V, 5A, 75W, >2MHz	16h	Mot	BD199, 2N5983, 2SD493
2N5978	Si-N	=2N5977: 80V	16h		2N5984, 2SD494
2N5979	Si-N	=2N5977: 100V	16h		2N5985, 29D495
2N596	Ge-P	NF/S, 35/35/30V, 0,5A, 0,25W, >5,6MHz	2a	USA	(ASY76..77)
2N5980	Si-P	NF/S-L, 60V, 6A, 90W, >2MHz	16h	Mot	BD208, MJE2955, 2N5968, 2SB578
2N5981	Si-P	=2N5980: 80V	16h		2N5987
2N5982	Si-P	=2N5980: 100V	16h		2N5988
2N5963	Si-N	NF/S-L, 80V, 6A, 90W, >2MHz	16h	Mot	BD207, MJE3055, 2N5989, 2SD491
2N5964	Si-N	=2N5963: 80V	16h		2N5990
2N5955	Si-N	=2N5983: 100V	16h		2N5991
2N5986	Si-P	NF/S-L, 80V, 12A, 100W, >2MHz	16h	Mot	—
2N5987	Si-P	=2N5988: 80V	16h		—
2N5988	Si-P	=2N5966: 100V	16h		—
2N5989	Si-N	NF/S-L, 80V, 12A, 100W, >2MHz	16h	Mot	—
2N599	Ge-P	NF/S, 30/20/20V, 0,5A, 0,25W, >10MHz	2a	USA	(ASY78..77)
2N5990	Si-N	=2N5989: 80V	16h		—
2N5991	Si-N	=2N5989: 100V	16h		—
2N5992	Si-N	FM/VHF-L, 65V, 5A, PQ>7W(86MHz)	55s	Rca	—
2N5993	Si-N	FM/VHF-L, 38V, 5A, PQ=20W(68MHz)	55s	Rca	—
2N5994	Si-N	VHF-L, 65V, 5A, PQ=35W(175MHz)	55s	Rca	BLW25, 2N5643, 2SC2689
2N5995	Si-N	VHF-L, 38V, 1,5A, PQ>7W(175MHz)	55s	Rca	2SC2281
2N5996	Si-N	VHF-L, 38V, 5A, PQ>15W(175MHz)	55s	Rca	BLW20, BLW31, 2N6064
2N5998	Si-N	NF-V, ra, 55V, 0,5A, 0,4W, 300MHz	7c	Gen, Sem, Spr	BC164, BC239, BC337..338, BC549, ++

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2N5999	Si-P	NF-V, ra, 35V, 0,5A, 0,4W, 300MHz	7c	Gen,Sem,Spr	BC214, BC309, BC327..328, BC559, ++
2N59A	Ge-P	=2N59: 40V	2a		ASY48, ASY76..77
2N59B	Ge-P	=2N59: 50V	2a		ASY48, ASY77
2N59C	Ge-P	=2N59: 60V	2a		ASY48, ASY77
2N600	Ge-P	NF/S, 35V, 0,5A, 0,75W, 10MHz	37d	Idi,Ssi	(AC128K, AC153K, ASY76..77)
2N6000	Si-N	Uni, ra, 35V, 0,5A, 0,4W, B>100	7a	Gen,Sem	BC184, BC239, BC337..338, BC549, ++
2N6001	Si-P	Uni, ra, 35V, 0,5A, 0,4W, B>100	7a	Gen,Sem	BC214, BC309, BC327..328, BC559, ++
2N6002	Si-N	=2N6000: B>250	7a		BC184, BC239, BC337..338, BC549, ++
2N6003	Si-P	=2N6001: B>250	7a		BC214, BC309, BC327..328, BC559, ++
2N6004	Si-N	Uni, ra, 50V, 0,5A, 0,4W, B>100	7a	Gen,Sem	BC337, BC414, BC550, BC637, ++
2N6005	Si-P	Uni, ra, 50V, 0,5A, 0,4W, B>100	7a	Gen,Sem	BC327, BC416, BC560, BC638, ++
2N6006	Si-N	=2N6004: B>250	7a		BC337, BC414, BC550, BC637, ++
2N6007	Si-P	=2N6005: B>250	7a		BC327, BC418, BC560, BC638, ++
2N6008	Si-N	NF, ra, 35V, 0,5A, 0,4W, 300MHz	7c	Gen,Sem,Spr	BC184, BC239, BC337..338, BC549, ++
2N6009	Si-P	NF, ra, 35V, 0,5A, 0,4W, 300MHz	7c	Gen,Sem,Spr	BC214, BC309, BC327..328, BC559, ++
2N601	Ge-P	NF/S, 30V, 0,5A, 0,75W, 18MHz	37d	Idi,Ssi	(AC128K, AC153K, ASY76..77)
2N6010	Si-N	Uni, ra, 50V, 0,8A, 0,5W, B>100	7a	Gen,Sem	BC337, BC637, BSV59, 2N2221..22(A), ++
2N6011	Si-P	Uni, ra, 50V, 0,8A, 0,5W, B>100	7a	Gen,Sem	BC327, BC638, BSW24, 2N2906..07(A), ++
2N6012	Si-N	=2N6010: B>250	7a		BC337, BC637, BSV59, 2N2221..22(A), ++
2N6013	Si-P	=2N6011: B<250	7a		BC327, BC638, BSW24, 2N2906..07(A), ++
2N6014	Si-N	Uni, ra, 70V, 0,8A, 0,5W, B>100	7a		BC639, BSV59, 2N2221..22A, 2SD667, ++
2N6015	Si-P	Uni, ra, 70V, 0,8A, 0,5W, B>100	7a		BC840, BSW24, 2N2906..07A, 2SB647, ++
2N6016	Si-N	=2N6014: B>250	7a		BC639, BSV59, 2N2221..22A, 2SD667, ++
2N6017	Si-P	=2N6015: B>250	7a		BC640, BSW24, 2N2906..07A, 2SB647, ++
2N602(A)	Ge-P	HF, 20..35V, 0,12W, 20MHz	2a	USA	AF124..126, AF200
2N6021	Si-P	NF/S-L, 60/70V, 4A, 36W, >0,8MHz	17j	Sem	BD244B, BD538, BD540B, BD952, ++
2N6022	Si-P	=2N6021	17j		BD244B, BD538, BD540B, BD952, ++
2N6023	Si-P	=2N6021: 80/40V	17j		BD244A BD538, BD540A BD950, ++
2N6024	Si-P	=2N6021: 60/40V	17j		BD244A BD538, BD540A BD950, ++
2N6025	Si-P	=2N6021: 80/60V	17j		BD244B, BD538, BD540B, BD952, ++
2N6026	Si-P	=2N6021: 80/60V	17j		BD244B, BD538, BD540B, BD952, ++
2N6027	PUT	Ip<5µA, Iv>70µA	7a(KGA)	Gen, Mot, Phi	2N6116, 2N6119, MPU131, MPU231
2N6028	PUT	=2N6027: Ip<1µA, Iv>25µA	7a(KGA)		2N6120
2N6029	Si-P	NF/S-L, 100V, 18A, 200W, >1MHz	23a	Fch, Mot, Stc	BD318, 2N6609, 2SA1117
2N6029	Si-P			Ker,Sgs	—
2N603(A)	Ge-P	HF, 30V, 0,12W, 40MHz	2a	USA	AF124..126, AF200
2N6030	Si-P	=2N6029: 120V	23a		MJ15016, 2N6609, 2SA1117
2N6031	Si-P	=2N6029: 140V	23a		MJ15016, 2N6609, 2SA1117
2N6032	Si-N	S-L, 120/90V, 50A, 140W, >50MHz	23a	USA,Rca	2N6275..77
2N6033	Si-N	S-L, 150/120V, 40A, 140W, >50MHz	23a	USA,Rca	2N6275..77
2N6034	Si-P-Darl+Di	NF/S-L, 40V, 4A, 40W, B>750	14b(B)	Mot,Nsc,Sgs	BD876, BD776
2N6035	Si-P-Darl+Di	=2N6034: 60V	14b(B)		BD678, BD778
2N6036	Si-P-Darl+Di	=2N6034: 60V	14b(B)		BD660, BD780
2N6037	Si-N-Darl+Di	NF/S-L, 40V, 4A, 40W, B>750	14b(A)	Mot,Nsc,Sgs	BD675, BD775
2N6038	Si-N-Darl+Di	=2N6037: 60V	14b(A)		BD677, BD777
2N6039	Si-N-Darl+Di	=2N6037: 80V	14b(A)		BD679, BD779
2N604(A)	Ge P	HF, 30V, 0,12W, 60MHz	2a	USA	AF124..126, AF200
2N6040	Si-P-Darl+Di	NF/S-L, 60V, 8A, 75W, B>1000	17c(B)	Mot,Nsc,Rca	BD646, BD898, BDW74A, BDX54A, ++
2N6040	Si-P-Darl+Di			Sgs	—
2N6041	Si-P-Darl+Di	=2N6040: 60V	17c(B)		BD646, BD900, BDW74B, BDX54B, ++
2N6042	Si-P-Darl+Di	=2N6040: 100V	17c(B)		BD650, BD902, BDW74C, BDX54C, ++
2N6043	Si-N-Darl+Di	NF/S-L, 60V, 8A, 75W, B>1000	17c(A)	Mot,Nsc,Rca	BD645, BD897, BDW73A, BDX53A, ++
2N6043	Si-N-Darl+Di			Sgs	—
2N6044	Si-N-Darl+Di	=2N6043: 60V	17c(A)		BD847, BD899, BDW73B, BDX53B, ++
2N6045	Si-N-Darl+Di	=2N6043: 100V	17c(A)		BD649, BD901, BDW73C, BDX53C, ++
2N6048	Si-N	S-L, 70V, 20A, 114W(Tc=100°), >30MHz	49m	USA,Tiw	2N2815..18, 2N2819..F1524322
2N6047	Si-N	=2N6046: 110V	49m		2N2817..18, 2N2621..22
2N6048	Si-N	=2N6048: 150V	49m		2N2817..18, 2N2821..22
2N6049	Si-P	NF/S-L, 90V, 4A, 75W, >3MHz	22a	USA, Mot	BD244C, BD540C, BD954, BDX14, ++
2N605	Ge-P	HF, 15V, 0,12W, 15MHz	2a	Sty	AF124..127, AF200
2N6050	Si-P-Darl+Di	NF/S-L, 60V, 12A, 150W, B>750	23a(B)	Fch,Mot,Rca	BDV66, BDW84A, BDX64, BDX88A, ++
2N6050	Si-P-Darl+Di			Sgs,Stc,Tix	—
2N6051	Si-P-Darl+Di	=2N6050: 80V	23a(B)		BDV88A, BDW84B, BDX84A, BDX88B, ++
2N6052	Si-P-Darl+Di	=2N6050: 100V	23a(B)		BDV68A, BDW84C, BDX84B, BDX88C, ++
2N6053	Si-P-Darl+Di	NF/S-L, 60V, 8A, 100W, B>750	23a(B)	Fch,Mot,Rca	BDV84, BDX62, MJ900, TIP145, ++
2N6053	Si-P-Darl+Di			Sgs,Stc	—

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2N6054	Si-P-Darl+Di	=2N6053: 60V	23a(B)		BDV64A, BDX62A, MJ901, TIP146,++
2N6055	Si-N-Darl+Di	NF/S-L, 60V, 8A, 100W, B>750	23a(A)	Fch, Mot, Rca	BDV65, BDX63, MJ1000, TIP140,++
2N6055	Si-N-Darl+Di			Sgs, Stc	—
2N6056	Si-N-Darl+Di	=2N6055: 90V	23a(A)		BDV65A, BDX63A, MJ1001, TIP141,++
2N6057	Si-N-Darl+Di	NF/S-L, 60V, 12A, 150W, B>750	23a(A)	Fch, Mot, Rca	BDV67, BDW83A, BDX65, BDX87A,++
2N6057	Si-N-Darl+Di			Sgs, Stc, Tix	—
2N6058	Si-N-Darl+Di	26057: 60V	23a(A)		BDV67A, BDW83B, BDX65A, BDX87B,++
2N6059	Si-N-Darl+Di	=2N6057: 100V	23a(A)		BDV65A, BDW83C, BDX65B, BDX87C,++
2N606	Ge-P	HF, 15V, 0,12W, 20MHz	2a	Sty	AF124..127, AF200
2N6060	Si-N	S-L, 100/100V, 50A, 225W, >10MHz	49m	USA	2N6278..81
2N6061	Si-P	S-L, 100/100V, 50A, 225W, >10MHz	49m	USA	2N6380..82
2N6062	Si-N	=2N6060: Iso	49a		—
2N6063	Si-P	=2N6061: Iso	49a		—
2N6064	Ge-P	S-L, 80V, 10A, 56W	≈2a	Mot	—
2N6065	Ge-P	=2N6064: 120V	≈2a		—
2N6066	Ge-P	=2N6064: 160V	≈2a		—
2N6067	Si-P	S, 50V, 1A, 0,625W, <45/95ns	7e	Mot	2N4026..29
2N6068	Triac	25V, 4A(Tc=65°), Igt/Ih<30/<30mA	14j	Mot, Tag	TAG96A, (TAG136A, Z0410A, TAG231-200)
2N6068...6075A	Triac	=2N6068..6075: Igt/Ih<10/<15mA	14j		TAG97.., (TAG137.., Z0409.., TAG232..)
2N6068...6075B	Triac	=2N6068..6075: Igt/Ih<5/<15mA	14j		TAG98.., (TAG136.., Z0405.., TAG233..)
2N6069	Triac	=2N6068: 50V	14j		TAG96A, (TAG136A, Z0410A, TAG231-200)
2N607	Ge-P	HF, 15V, 0,12W, 25MHz	2a	Sty	AF124..126, AF200
2N6070	Triac	=2N6068: 100V	14j		TAG96A, (TAG136A, Z0410A, TAG231-200)
2N6071	Triac	=2N6068: 200V	14j		TAG96B, (TAG136B, Z0410B, TAG231-200)
2N6072	Triac	=2N6068: 300V	14j		TAG96C, (TAG136C, Z0410C, TAG231-400)
2N6073	Triac	=2N6068: 400V	14j		TAG96D, (TAG136D, Z0410D, TAG231-400)
2N6074	Triac	=2N6068: 500V	14j		TAG96E, (TAG136E, Z0410E, TAG231-600)
2N6075	Triac	=2N6068: 600V	14j		TAG96M, (TAG136M, Z0410M, TAG231-600)
2N6076	Si-P	Uni, 25V, 0,1A, 0,36W, 200MHz	7c	USA, Gen, Nsc	BC213, BC258, BC308, BC556,++
2N6077	Si-N	S-L, 300/275V, 7A, 45W, 7MHz	22a	USA, Mot, Rca	BU406..406, BUT56(A), 2SC1865,++
2N6078	Si-N	S-L, 275/250V, 7A, 45W, 7MHz	22a		BU406..406, BUT56(A), 2SC1865,++
2N6079	Si-N	S-L, 375/350V, 7A, 45W, 7MHz	22a		BU406, BU406, BUT56(A), 2SC1865,++
2N608	Ge-P	HF, 15V, 0,12W, 35MHz	2a	Sty	AF124..126, AF200
2N6080	Si-N	VHF-Tr/E, 36V, 1A, PQ=4W(175MHz)	55r	Mot, Sem, Tho	BLY65
2N6080	Si-N			Tix, Trw	—
2N6081	Si-N	VHF-L, 36V, 2,5A, PQ=15W(175MHz)	55r	=2N6080	BLW29, BLY84, BLY88, MRF226
2N6082	Si-N	VHF-L, 36V, 5A, PQ=25W(175MHz)	55r	=2N6080	BLY89, MRF209, 2N5591
2N6083	Si-N	VHF-L, 36V, 5A, PQ=30W(175MHz)	55r	=2N6080	MRF236
2N6084	Si-N	VHF-L, 36V, 7A, PQ=40W(175MHz)	55r	=2N6080	BLW60
2N6085	Si-N	Dual, 45V, 0,03A, 0,6W, >60MHz	TO-77	Tsc	2N3728..29, 2N3411
2N6086	Si-N	Dual, 45V, 0,03A, 0,6W, >60MHz	TO-77	Tsc	2N3728..29, 2N3411
2N6087	Si-N	Dual, 45V, 0,03A, 0,6W, >60MHz	TO-77	Tsc	2N3726..29, 2N3411
2N6088	Si-N	Dual, 45V, 0,03A, 0,6W, >60MHz	TO-77	Tsc	2N3728..29, 2N3411
2N6089	Si-N	Dual, 45V, 0,03A, 0,6W, >60MHz	TO-77	Tsc	2N3728..29, 2N3411
2N609	Ge-P	NF, 25V, 0,2A, 0,18W, B=100	2a	USA	AC125..126, AC151, 2SB54, 2SB56
2N6090	Si-N	Dual, 45V, 0,03A, 0,6W, >60MHz	TO-77	Tsc	2N3726..29, 2N3411
2N6091	Si-N	Dual, 45V, 0,03A, 0,6W, >60MHz	TO-77	Tsc	2N3728..29, 2N3411
2N6092	Si-N	Dual, 45V, 0,03A, 0,6W, >60MHz	TO-77	Tsc	2N3728..29, 2N3411
2N6093	Si-N	AM-SSB-L, 70V, 10A, PEP=75W(30MHz)+C15388		Rca, Tho	—
2N6094	Si-P	VHF-L, 36V, 1A, PQ=4W(175MHz)	59r	Mot	—
2N6095	Si-P	VHF-L, 36V, 2,5A, PQ=15W(175MHz)	59r	Mot	—
2N6096	Si-P	VHF-L, 36V, 4A, PQ=30W(175MHz)	59r	Mot	—
2N6097	Si-P	VHF-L, 36V, 4A, PQ=40W(175MHz)	59r	Mot	—
2N6098	Si-N	NF/S-L, 70V, 10A, 75W, >0,8MHz	17j	USA, Rca, Tho	BD709, BD743A, BD607, BD909,++
2N6099	Si-N	=2N6098	17j		BD709, BD743A, BD807, BD909,++
2N60A..C	Ge-P	=2N59A..C: B=65	2a	USA	→2N59A..C
2N610	Ge-P	=2N609: B=80	2a	USA	AC125..126, AC151, 2SB54, 2SB56
2N6100	Si-N	=2N6098: 60V	17j		BD709, BD743B, BD609, BD909,++
2N6101	Si-N	=2N6098: 80V	17j		BD709, BD743B, BD809, BD909,++
2N6102	Si-N	=2N6098: 45V, 18A	17j		BD743, BD905, BDT81
2N6103	Si-N	=2N6098: 45V, 18A	17j		BD743, BD905, BDT81
2N6104	Si-N	UHF-L, 65V, 4,5A, PQ>30W(400MHz)	60e	Rca	—
2N6105	Si-N	UHF-L, 65V, 4,5A, PQ>30W(400MHz)	55s		—
2N6106	Si-P	NF/S-L, 60V, 7A, 40W, >10MHz	17j	USA, Mic, Mot	BD244B, BD544B, BD800, BD810,++
2N6106	Si-P			Nsc, Rca, Tho	—
2N6107	Si-P	=2N6106	17j		BD244B, BD544B, BD800, BD810,++

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2N6108	Si-P	=2N6106: 60V	17j		BD244A, BD544A, BD798, BD808, ++
2N6109	Si-P	=2N6106: 60V	17j		BD244A, BD544A, BD798, BD808, ++
2N611	Ge-P	=2N609: B=60	2a	USA	AC125..126, AC151, 2SB54, 2SB56
2N6110	Si-P	=2N6106: 40V	17j		BD244, BD544, BD798, BD808, ++
2N6111	Si-P	=2N6106: 40V	17j		BD244, BD544, BD798, BD808, ++
2N6112	Si-N	Uni, 50V, 0,36W, >160MHz	10b	Upl	BC167, BC182, BC237, BC547, ++
2N6114	UJT-N	Ip<5µA, Iv>1mA	5e	Gen,Mot	—
2N6115	UJT-N	=2N6114: Ip<15µA	5e		—
2N6116	PUT	Ip<5µA, Iv>70µA	2a(KGA)	Gen,Mot	2N6027, 2N6119, MPU131, MPU231
2N6117	PUT	=2N6116: Ip<2µA, Iv>50µA	2a(KGA)		MPU132, MPU232
2N6118	PUT	=2N6116: Ip<1µA, Iv>50µA	2a(KGA)		MPU133, MPU233
2N6119	PUT	Ip<5µA, Iv>70µA	2a(KGA)	Uni	2N6027, 2N6116, MPU131, MPU231
2N612	Ge-P	=2N609: B=25	2a	USA	AC125..126, AC151, 2SB54, 2SB56
2N6120	PUT	=2N6119: Ip<1µA, Iv>25µA	2a(KGA)		2N6028
2N6121	Si-N	NF/S-L, 45V, 4A, 40W, >2,5MHz	17j	Fch,Mic,Mot	BD243, BD533, BD539, BD947, ++
2N6121	Si-N			Nsc,Rca,Sgs	—
2N6122	Si-N	=2N6121: 60V	17j		BD243A, BD535, BD539A, BD949, ++
2N6123	Si-N	=2N6121: 60V	17j		BD243B, BD537, BD539B, BD951, ++
2N6124	Si-P	NF/S-L, 45V, 4A, 40W, >2,5W	17j	=2N6121	BD244, BD534, BD540, BD948, ++
2N6125	Si-P	=2N6124: 60V	17j		BD244A, BD536, BD540A, BD950, ++
2N6126	Si-P	=2N6124: 60V	17j		BD244B, BD536, BD540B, BD952, ++
2N6127	Si-P	S-L, 100V, 10A, 100W(Tc=50°), >40MHz	49a	Ker,Sol,Ssi	2N5290..91
2N6127	Si-P			Stc,Tix	—
2N6128	Si-N	S-L, 100V, 10A, 100W(Tc=50°), >50MHz	49a	Ker,Sol,Ssi	2N5288..89
2N6126	Si-N			Stc,Tix	—
2N6129	Si-N	NF/S-L, 40V, 7A, 50W, >2,5MHz	17j	Fch,Mic,Nsc	BD543, BD705, BD795, BD805, ++
2N6129	Si-N			Ssi,Rca	—
2N613	Ge-P	=2N609: B=33	2a	USA	AC125..126, AC151, 2SB54, 2SB56
2N6130	Si-N	=2N6129: 60V	17j		BD543A, BD707, BD797, BD607, ++
2N6131	Si-N	=2N6129: 60V	17j		BD543B, BD709, BD799, BD809, ++
2N6132	Si-P	NF/S-L, 40V, 7A, 50W, >2,5MHz	17j	=2N6129	BD544, BD706, BD796, BD808, ++
2N6133	Si-P	=2N6132: 60V	17j		BD544A, BD708, BD798, BD808, ++
2N6134	Si-P	=2N6132: 60V	17t		BD544B, BD710, BD800, BD810, ++
2N6135	Si-N	UHF, 35V, 0,25A, 2,5W, >1100MHz		Mot	—
2N6136	Si-N	UHF-L, 36V, 6A, PQ=25W(470MHz)	55r	Mot	2SC1339, 2SC2173
2N6137	PUT	Iv>70µA	2a(KGA)	Mot,Uni	—
2N6136	PUT	=2N6138	2a(KGA)		—
2N6139	Triac	200V, 10A(Tc=75°), Igt/Ih<75/<40mA	21l	Mot	T4110E, 2N5573, T6411B, 2N6160, T6410B
2N614	Ge-P	HF/S, 20V, 0,15A, 0,125W, 3MHz	2a	USA	ASY26..27, ASY76..77
2N6140	Triac	=2N6139: 400V	21l		T4110E, 2N5574, T6411D, 2N6161, T6410D
2N6141	Triac	=2N6139: 600V	21l		T4110M, T6411M, 2N6162, T6410M, 2N5446
2N6142	Triac	=2N6139	21l		→2N6139
2N6143	Triac	=2N6140	21j		→2N6140
2N6144	Triac	=2N6141	21j		→2N6141
2N6145	Triac	=2N5571	54l	Mot	T6421B, 2N6163, T6420B
2N6146	Triac	=2N5572	54l	Mot	T6421D, 2N6164, T6420D
2N6147	Triac	=T4100M	54l	Mot	T6421M, 2N6165, T6420M
2N615	Ge-P	HF/S, 20V, 0,15A, 0,125W, 5MHz	2a	USA	ASY26..27, ASY76..77
2N6151	Triac	=2N6139	16j	Mot	—
2N6152	Triac	=2N6140	16j	Mot	—
2N6153	Triac	=2N6141	16j	Mot	—
2N6154	Triac	200V, 10A, Igt<50mA	16j	Mot	—
2N6155	Triac	=2N6154: 400V	16j	Mot	—
2N6156	Triac	=2N6154: 600V	16j	Mot	—
2N6157	Triac	200V, 30A(Tc=65°), Igt/Ih<100/<60mA	29l	Mot	T6401B, T6400B, 2N5441
2N6156	Triac	=2N6157: 400V	29l		T6401D, T6400D, 2N5442
2N6159	Triac	=2N6157: 600V	29l		T6401M, T6400M, 2N5443
2N616	Ge-P	HF/S, 15V, 0,15A, 0,125W, 9MHz	2a	USA	ASY26..27, ASY76..77
2N6160	Triac	=2N6157	21l		T6411B, T6410B, 2N5444
2N6161	Triac	=2N6156	21l		T6411D, T6410D, 2N5445
2N6162	Triac	=2N6159	21l		T6411M, T6410M, 2N5446
2N6163	Triac	=2N6157: Iso	54l		T6421B, T6420B
2N6164	Triac	=2N6158: Iso	54l		T6421D, T6420D
2N6165	Triac	=2N6159: Iso	54l		T6421M, T6420M
2N6166	Si-N	VHF-L, 65V, 9A, PQ=100W(150MHz)	59r	Mot,Tix	BLW78
2N6187	50Hz-Thy	100V, 13A(Tc=65°), Igt/Ih<40/50mA	54b	Mot	2N6171, MCR65-3

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2N6168	50Hz-Thy	=2N6167: 200V	54b		2N6172, MCR65-4
2N6169	50Hz-Thy	=2N6167: 400V	54b		2N6176, MCR65 6
2N617	Ge-P	HF/S, 15V, 0,15A, 0,125W, 7,5MHz	2a	USA	ASY26..27, ASY76..77
2N6170	50Hz-Thy	=2N6167: 600V	54b		2N6174, MCR65-8
2N6171	50Hz-Thy	=2N3870	54b	Mot	MCR65-3
2N6172	50Hz-Thy	=2N3671	54b		MCR65-4
2N6t73	50Hz-Thy	=2N3872	54b		MCR65-6
2N6174	50Hz-Thy	=2N3873	54b		MCR65-6
2N6175	Si-N	NF/Vid, -L, 300V, 1A, 20W, >21MHz	14m	Rca	(BD410, BUV63, 2SC3051, 26C3425, ++)
2N6176	Si-N	=2N6175: 350V	t4m	Rca	(BD4t0, BUV63, 2SC3051, 2SC3425, ++)
2N6177	Si-N	=2N6175: 450V	14m	Rca	(BD410, BUV63, 26C3051, 26C3425, ++)
2N6178	Si-N	NF/S-L, 100V, 2A, 25W, >50MHz	14m	Rca	(BD139, BD230, BD379, BD529, ++)
2N6179	Si-N	=2N6178: 75V	14m		(BD139, BD230, BD377, BD527, ++)
2N618	Ge-P	NF/S-L, 80V, 3A, 106W	23a	USA, Mot	2N1541..43, 2N1546..48, 2N3615..16, ++
2N6180	Si-P	NF/S-L, 100V, 2A, 25W, >50MHz	14m	Rca	(BD140, BD231, BD380, BD530, ++)
2N6161	Si-P	=2N6182: 75V	14m		(BD140, BD231, BD376, BD528, ++)
2N6182	Si-P	S-L, 80/80V, 10A, 80W, >30MHz, B>30	49m	Sca, Ssi, Stc	(2N5290..91)
2N6182	Si-P			Tra	—
2N6183	Si-P	=2N6162: B>80	49m		(2N5290..91)
2N6184	Si-P	=2N6162: 100V	49m		(2N5290..91)
2N6185	Si-P	=2N6162: 100V, B>60	49m		(2N5290..91)
2N6t66	Si-P	=2N6182: Iso	49a	USA, Mot	(2N5290..91)
2N6167	Si-P	=2N6163: Iso	49a		(2N5290..91)
2N6168	Si-P	=2N6164: Iso	49a		(2N5290..91)
2N6189	Si-P	=2N6165: Iso	49a		(2N5290..91)
2N619	Si-N	Uni, 50V, 0,05A, 0,25W, B>9	2a	Sea	BC167, BC182, BC237, BC547, ++
2N6190	Si-P	S, 80V, 5A, 10W(Tc=100°), >30MHz, B>30	2a	Mot, Sca, Ssi	BFT35..37, BUY90
2N6190	Si-P			Sol, Stc	—
2N6191	Si-P	=2N6190. B>80	2a		BFT36..37, BUY90
2N6192	Si-P	=2N6190: 100V	2a		BFT36..37, BUY90
2N6193	Si-P	=2N6190: t00V, B>60	2a		BFT36..37, BUY90
2N6194	Si-N	HF-L, 50V, 5W	62a	Trw	—
2N6195	Si-N	HF-L, 50V, 10W	62a	Trw	—
2N6196	Si-N	HF-L, 50V, 20W	62a	Trw	—
2N6197	Si-N	HF-L, 60V, 1A, 10W	55r	Ctr	—
2N6196	Si-N	HF-L, 80V, 2,5A, 25W	55r	Ctr	—
2N6199	Si-N	HF-L, 80V, 5A, 50W	55r	Ctr	—
2N6t A..C	Ge-P	=2N59A..C: B=45	2a	USA	→2N59A. C
2N82	Ge-P	NF, 35V, 0,02A, 0,05W	37d	Phc	AC125..126, AC151
2N620	Si-N	=2N619: B>16	2a	Sca	BC167, BC182, BC237, BC547, ++
2N8200	Si-N	HF-L, 60V, 6,5A, 85W	55r	Ctr	—
2N8201	Si-N	HF-L, 80V, 12A, 140W	55r	Ctr	—
2N8202	Si-N	HF-L, 80V, 0,5A, 10W	55r	Ctr	—
2N6203	Si-N	HF-L, 80V, 1A, 20W	55r	Ctr	—
2N6204	Si-N	HF-L, 60V, 2A, 40W	55r	Ctr	—
2N6205	Si-N	HF-L, 80V, 4A, 80W	55r	Ctr	—
2N6206	Si-N	HF-L, 50V, 0,5A, 10W	55r	Ctr	—
2N6207	Si-N	HF-L, 50V, 1A, 20W	55r	Ctr	—
2N6206	Si-N	HF-L, 50V, 2A, 40W	55r	Ctr	—
2N621	Si-N	=2N619: B>36	2a	Sca	BC167, BC182, BC237, BC547, ++
2N821t	Si-P	NF/S-L, 275/225V, 2A, 35W, >20MHz	22a	Mot, Rca, Stc	BUX66A. C, 2SA1009(A), 2SAt236, 2SA1397
2N8212	Si-P	=2N8211: 350/300V	22a		BUX68B..C, 2SA1009(A), 2SA1236, 2SA1397
2N6213	Si-P	=2N821t: 400/350V	22a		BUX66A..C, 2SA1009A, 2SA1236, 2SA1397
2N6214	Si-P	=2N8211: 450/400V	22a		2N6422..23
2N6215	Si-N	S-L, 100V, 50A, 125W(Tc=100°), >20MHz	49m	Sol, Ssi, Stc	2N6060, 2N8276..81
2N8216	Si-N	S-L, 200V, 10A, 71W(Tc=100°), >20MHz	23a	Ker, Stc	BUX17(A..C), BUX42..43, BUY18, ++
2N6217	Si-N	=2N8216: 180V	23a		BUX17(A..C), BUX42..43, BUY18, ++
2N6218	Si-N	S/Vid, 300V, 0,05A, 0,5W, >50MHz	7a	Gen, Mic, Sem	BF299, BF420, BF483, 2SC3468, ++
2N6219	Si-N	=2N6216: 250V	7a		BF298..299, BF420, BF483, 2SC3466, ++
2N622	Si-N	Uni, 50V, 0,05A, 0,386W	2a	Idi, Sca	BC167, BC182, BC237, BC547, ++
2N8220	Si-N	=2N6216: 200V	7a		BF298..299, BF422, BF463, 2SC3468, ++
2N6221	Si-N	=2N6216: 150V	7a		BF297..299, BF422, BF483, 2SC3468, ++
2N6222	Si-N	NF, 80V, 0,1A, 0,36, B>75	7a	Gen, Sem, Spr	BC174, BC182, BC190, BC546, ++
2N6223	Si-P	NF, 80V, 0,1A, 0,36W, B>75	7a	Gen, Sem, Spr	BC212, BC256, BC268, BC556, ++
2N6224	Si-N	=2N6222: B>150	7a		BC174, BC18+F154432, BC190, BC546, ++
2N8225	Si-P	=2N6223: B>150	7a		BC212, BC256, BC256, BC556, ++

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2N6226	Si-P	NF/S-L, 100V, 6A, 150W, >1MHz	23a	USA, Mot	BD246C, BDV96, BDX96, 2N6229..31, ++
2N6227	Si-P	=2N6226: 120V	23a		BD246D, 2N6230..31, 2SA1116..17, ++
2N6226	Si-P	=2N6226: 140V	23a		BD246D, 2N6231, 2SA1116..17, 2SB555, ++
2N6229	Si-P	NF/S-L, 100V, 10A, 150W, >1MHz	23a	USA, Mot	BD318, 2N6029..31, 2SA1116..17, ++
2N623	Ge-P	HF, 30V, 90MHz		Sty	AF124, AF106, AF200
2N6230	Si-P	=2N6229: 120V	23a		MJ15016, 2N6030..31, 2SA1116..17, ++
2N6231	Si-P	=2N6229: 140V	23a		MJ15016, 2N6031, 2SA1116..17, 2SB555, ++
2N6232	Si-N	S-L, 140V, 10A, 15W(Tc=25°), >30MHz	2a	Sca, Stc, Uni	BUY62
2N6232-4	Si-N	S-L, 140V, 10A, 15W(Tc=25°), >30MHz	2a*		(BUY82)
2N6233	Si-N	S-L, 250/225V, 5A, 50W, >20MHz	22a	Mot, Stc, Uni	BUT56(A), BUX63, 2SC2907, 2SC3035, ++
2N6234	Si-N	=2N6233: 300/275V	22a		BUT56(A), BUX63, 2SC2907, 2SC3035, ++
2N6235	Si-N	=2N6233: 350/325V	22a		BUT56(A), BUX63, 2SC2907, 2SC3035, ++
2N6236	50Hz-Thy	30V, 2,6A(Tc=90°), Igt/Ih<0,2/<5mA	14e	Mot, Tag	MCR106-1, (C106Y, TAG106Y, S2060Y, ++)
2N6237	50Hz-Thy	=2N6236: 50V	14e		MCR106-2, (C106F, TAG106F, S2060F, ++)
2N6236	50Hz-Thy	=2N6236: 100V	14e		MCR106-3, (C106A, TAG106A, S2060A, ++)
2N6239	50Hz-Thy	=2N6236: 200V	14e		MCR106-4, (C106B, TAG106B, S2060B, ++)
2N624	Ge-P	HF, 30V, 10mA, 0,1W, >12MHz	5g	Etc, Syl	AF124..127, AF200
2N6240	50Hz-Thy	=2N6236: 400V	14e		MCR106-6, (C106D, TAG106D, S2060D, ++)
2N6241	50Hz-Thy	=2N6236: 600V	14e		MCR106-8, (C106M, TAG106M, S2060M, ++)
2N6246	Si-P	NF/S-L, 70V, 15A, 125W, >6MHz	23a	USA, Rca, Tix	BD316, BD546B, MJ2955, 2N6029..31, ++
2N6247	6i-P	=2N6246: 90V	23a		BD318, BD546C, MJ2955, 2N6029..31, ++
2N6246	Si-P	=2N6246: 110V	23a		BD318, BD546D, MJ2955, 2N6030..31, ++
2N6249	Si-N	S-L, 300/200V, 10A, 175W, 8MHz	23a	USA, Mot, Rca	BUX17A, F15501C, BUW24..25, BUW72, ++
2N6249	Si-N			Tho, Tix, Tos	—
2N625	Ge-N	NF/S, 40V, 1A	2a	Syl	—
2N6250	Si-N	=2N6249: 375/275V	23a		BUX17B,C, BUW24..25, BUW34, BUW72, ++
2N6251	Si-N	=2N6249: 450/350V	23a		BUX17C, BUW24..25, BUW34, BUW72, ++
2N6253	Si-N	NF/S-L, 55V, 15A, 115W, >0,6MHz	23a	USA, Rca, Tix	BD315, BD545A, 2N3055, 2N5881..82, ++
2N6254	Si-N	NF/S-L, 100V, 15A, 150W, >0,6MHz	23a	USA, Rca, Tix	BD317, BD545C, 2N3772, 2N5629..31, ++
2N6255	Si-N	VHF-Tr/E, 36V, 1A, PQ=3W(175MHz)	2a	Ker, Mot, Whs	BFQ43, BFS22, BFW46, 2N3924
2N6256	Si-N	UHF-Tr/E, 36V, 0,4A, PQ=0,5W(470MHz)	51r	Mot	BLU96, MRF627..628
2N6257	Si-N	NF/S-L, 50V, 20A, 150W, >0,8MHz	23a	USA, Mot, Rca	BD364, BDX40..41, 2N3771..72, ++
2N6258	Si-N	NF/S-L, 100V, 30A, 250W, >0,8MHz	23a	USA, Mot, Rca	BDY29, MJ802, 2SD797
2N6259	Si-N	NF/S-L, 170V, 16A, 250W, >0,2MHz	23a	USA, Mot, Rca	BDW14, BDY56, 2SC2607..06, 2SD753, ++
2N626	Ge/Si-N-Darl	30V, B>16000		Sty	—
2N6260	Si-N	NF/S-L, 50V, 3A, 29W, >0,8MHz	22a	USA, Rca	BD241, BD535, BD935, 2N4231..33, ++
2N6261	Si-N	NF/S-L, 90V, 4A, 50W, >0,8MHz	22a	USA, Rca	BD243B, BD539C, BD953, 2N3054, ++
2N6262	Si-N	NF/S-L, 170V, 10A, 150W, >0,6MHz	23a	USA, Rca, Tix	BD745F, BDY54, 2SC2607..06, 2SD753, ++
2N6263	Si-N	NF/S-L, 140V, 3A, 20W, >0,2MHz	22a	U6A, Rca	BD241D, BD243D, 2N3441, 2SD608, ++
2N6264	Si-N	NF/S-L, 170V, 3A, 50W, >0,2MHz	22a		BD241E, BD243E, 2SD386(A)
2N6265	Si-N	UHF-Tr/E, 50V, 0,275A, PQ>2W(2GHz)	62a	Rca	—
2N6266	Si-N	UHF-L, 50V, 1A, PQ>5W(2GHz)	62a	Rca	—
2N6267	Si-N	UHF-L, 50V, 1,5A, PQ>10W(2GHz)	62a	Rca	—
2N6266	Si-N	UHF-Tr/E, 45V, 0,35A, PQ>2W(2,3GHz)	62a	Rca	—
2N6269	Si-N	UHF-L, 45V, 1,5A, PQ>6,5W(2,3GHz)	62a	Rca	—
2N627	Ge-P	NF/S-L, 40V, 10A, 94W	23a	USA, Mot	AL100..101, AUY21, 2N2268..93, ++
2N6270	Si-N	S-L, 100V, 30A, 150W(Tc=100°), >75MHz	23a	USA, Tix	2N5671
2N6271	Si-N	=2N6270: 120V	23a		2N5671
2N6272	Si-N	=2N6270:	49m		2N2624..25
2N6273	Si-N	=2N6270: 120V	49m		2N2825
2N6274	Si-N	S-L, 120V, 50A, 250W, >30MHz	23a	Mot, Ker, Ssi	2N6032..33
2N6274	Si-N			Stc	—
2N6275	Si-N	=2N6274: 140V	23a		2N6033
2N6276	Si-N	=2N6274: 160V	23a		—
2N6277	Si-N	=2N6274: 160V	23a		—
2N6276	Si-N	=2N6274:	49m		—
2N6279	Si-N	=2N6274: 140V	49m		—
2N626	Ge-P	=2N627: 60V	23a	USA, Mot	AL100..101, AUY21, 2N2292..93, ++
2N6260	Si-N	=2N6274: 160V	49m		—
2N6281	Si-N	=2N6274: 160V	49m		—
2N6282	Si-N-Darl+Di	NF/S-L, 60V, 20A, 160W, B>750	23a(A)	USA, Lbd, Mot	BDX69(A..C), MJ11012, 2SD730, 2SD1460
2N6282	Si-N-Darl+Di			Rca, Sgs	—
2N6283	Si-N-Darl+Di	=2N6282: 60V	23a(A)		BDX69A..C, MJ11014, 2SD730, 2SD1460
2N6264	Si-N-Darl+Di	=2N6282: 100V	23a(A)		BDX69B..C, MJ11016, 2SD730, 2SD1460
2N6285	Si-P-Darl+Di	NF/S-L, 60V, 20A, 160W, B>750	23a(B)	USA, Lbd, Mot	BDX66(A..C), MJ11011, 2SB694
2N6265	Si-P-Darl+Di			Rca, Sgs	—

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2N6286	Si-P-Darl+Di	=2N6265: 80V	23a(B)		BDX66A..C, MJ11013, 2SB694
2N6287	Si-P-Darl+Di	=2N6285: 100V	23a(B)		BDX66B..C, MJ11015, 2SB694
2N6286	Si-N	NF/S-L, 40V, 7A, 40W, >4MHz	17j	Fer,Mic,Mot	BD243, BD543, BD795, BD805, ++
2N6288	Si-N			Nsc,Rca,Sgs	—
2N6269	Si-N	=2N6288	17j		BD243, BD543, BD795, BD805, ++
2N629	Ge-P	=2N627: 80V	23a	USA, Mot	AL100..101, AUY37, 2N2292..93, ++
2N6290	Si-N	=2N6286: 80V	17j		BD243A, BD543A, BD797, BD807, ++
2N6291	Si-N	=2N6288: 80V	17j		BD243A, BD543A, BD797, BD807, ++
2N6292	Si-N	=2N6286: 80V	17j		BD243B, BD543B, BD799, BD809, ++
2N6293	Si-N	=2N6288: 80V	17j		BD243B, BD543B, BD799, BD809, ++
2N6294	Si-N-Darl+Di	NF/S-L, 80V, 4A, 50W, B>750	23a(A)	Mot,Stc	BD645, BD897, BDW23A, BDW63A, ++
2N6295	Si-N-Darl+Di	=2N6294, 80V	23a(A)		BD647, BD899, BDW23B, BDW63B, ++
2N6296	Si-P-Darl+Di	NF/S-L, 60V, 4A, 50W, B>750	23a(B)	Mot,Stc	BD646, BD896, BDW24A, BDW64A, ++
2N6297	Si-P-Darl+Di	=2N6296: 80V	22a		BD646, BD900, BDW24B, BDW64B, ++
2N6296	Si-P-Darl+Di	=2N6040, 2N6042	17c	Mot,Stc	BD646, BD896, BDW74A, BDX54A, ++
2N6299	Si-P-Darl+Di	=2N6040, 2N6042	17c	Mot,Stc	BD648, BD900, BDW74B, BDX54B, ++
2N63	Ge-P	NF, 30V, 0,5A, 0,1W	3a	USA	AC125..126, AC151
2N630	Ge-P	=2N627: 100V	23a	USA, Mot	AL100..101, AUY37, 2N2290, 2N2293, ++
2N6300	Si-N-Darl+Di	=2N6043	17c(A)	Mot,Stc	BD645, BD897, BDW73A, BDX53A, ++
2N6301	Si-N-Darl+Di	=2N6044	17c(A)	Mot,Stc	BD647, BD899, BDW73B, BDX53B, ++
2N6302	Si-N	S-L, 140V, 15A, 150W, >0,2MHz	23a	Ker,Stc,Tix	BD745E, BDX50, 2N3773, 2SC2608
2N6303	Si-P	S, 80V, 3A, 1W, >80MHz, <100/400ns	2a	USA,Mot,Sgs	—
2N6304	Si-N	UHF, 30V, 0,05A, 0,2W, >1400MHz	5g	Mot,Sca	BFS55, BFR37, BFW30, BFX73, ++
2N6305	Si-N	UHF, 30V, 0,05A, 0,2W, >1200MHz	5g	Mot,Sca	BFS55, BFR37, BFW30, BFX73, ++
2N6306	Si-N	S-L, 500/250V, 8A, 125W, >5MHz	23a	USA,Mot,Rca	BUS12(A), BUW25..26, BUW34..36, ++
2N6306	Si-N			Tix	—
2N6307	Si-N	=2N6306: 600/300V	23a		BUS12(A), BUW25..26, BUW35..36, ++
2N6306	Si-N	=2N6306: 700/350V	23a		BUS12(A), BUW26, BUW35..36, ++
2N6309	Si-N	S-L, 120V, 90A, 400W, >30MHz	49m	Mot	—
2N631	Ge-P	NF, 25V, 0,05A, 0,167W	2a	USA	AC125..126, AC151, 2SB54, 2SB56
2N6310	Si-N	=2N6309: 140V	49m		—
2N6311	Si-N	=2N6309: 180V	49m		—
2N6312	Si-P	NF/S-L, 40V, 5A, 75W, >4MHz	22a	USA, Mot	BD244, BD540, BD948+F15608, 2SB550, ++
2N6313	Si-P	=2N6312: 60V	22a		BD244A, BD540A, BD950, 2SB550, ++
2N6314	Si-P	=2N6312: 80V	22a		BD244B, BD540B, BD952, 2SB550, ++
2N6315	Si-N	=2N5873: 90W	22a	Mot,Ssi,Stc	BD543A, BD797, BD807, 2N5428..30, ++
2N6316	Si-N	=2N5874: 90W	22a		BD543B, BD799, BD809, 2N5428..30, ++
2N6317	Si-P	=2N5871: 90W	22a		BD544A, BD798, BD808, 2N5954..55, ++
2N6318	Si-P	=2N5872: 90W	22a		BD544B, BD800, BD810, 2N5954, ++
2N6319	Si-N	S-L, 120/100V, 80A, 300W, >30MHz		Mot	—
2N632	Ge-P	NF, 30V, 0,05A, 0,187W	2a	USA	AC125..126, AC151, 2SB54, 2SB56
2N6320	Si-N	=2N6319: 140/120V		Mot	—
2N6321	Si-N	=2N6319: 160/140V		Mot	—
2N6322	Si-N	S-L, 300/200V, 30A, 350W, >10MHz	23a	USA, Tix	BUR21..22, BUV22..23, BUX22..23, ++
2N6323	Si-N	=2N6322: 400/300V	23a		BUV23, BUX23
2N6324	Si-N	=2N6322:	49m		—
2N6325	Si-N	=2N6322: 400/300V	49m		—
2N6326	Si-N	NF/S-L, 80V, 30A, 200W, >3MHz	23a	USA, Tix	BDY29, MJ802, 2N6270..72, 2SD797
2N6327	Si-N	=2N6326: 80V	23a		BDY29, MJ802, 2N6270..72, 2SD797
2N6328	Si-N	=2N6326: 100V	23a		BDY29, MJ802, 2N6270..72, 2SD797
2N6329	Si-P	NF/S-L, 60V, 30A, 200W, >3MHz	23a	USA, Tix	MJ4502
2N633	Ge-P	NF, 35V, 0,05A, 0,167W	2a	USA	AC125..126, AC151, 2SB54, 2SB56
2N6330	Si-P	=2N6329: 80V	23a		MJ4502
2N6331	Si-P	=2N6329: 100V	23a		MJ4502
2N6332	50Hz-Thy	30V, 2A(Tc=80°), Igt/Ih<0,2/<5mA	2a	Tag, Tix	TAG615-100, (C106Y, TAG106Y, ++)
2N6333	50Hz-Thy	=2N6332: 50V	2a		TAG615-100, (C106F, TAG106F, ++)
2N6334	50Hz-Thy	=2N6332: 100V	2a		TAG615-100, (C106A, TAG106A, ++)
2N6335	50Hz-Thy	=2N6332: 200V	2a		TAG615-200, (C106B, TAG106B, ++)
2N6336	50Hz-Thy	=2N6332: 300V	2a		TAG615-400, (C106C, TAG106C, ++)
2N6337	50Hz-Thy	=2N6332: 400V	2a		TAG615-400, (C106D, TAG106D, ++)
2N6336	Si-N	S-L, 120V, 25A, 200W, >40MHz	23a	USA, Mot, Tix	BDW30, 2N5671..72, 2N6272, 2N6274..77
2N6339	Si-N	=2N6338: 140V	23a		BDW30, BDY58; 2N5672, 2N6275..77
2N634(A)	Ge-N	NF/S, 20..25V, 0,3A, 0,15W, 8MHz	2a(B=case)	USA	ASY26..29, ASY73..75
2N6340	Si-N	=2N6338: 180V	23a		BDW32, BDY58, 2N6276..77
2N6341	Si-N	=2N6338: 180V	23a		BDW34, 2N6277
2N6342	Triac	200V, 8A(Tc=80°), Igt/Ih<50/<40mA	17j	Mot, Rca, Tag	T2802B, MAC222-4, TIC226B, TXD10K40, ++

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2N6342A	Triac	=2N6342: 12A(Tc=80°)	17j		TIC236B, TW11N400, TXD10K40P, MAC15-4,++
2N6343	Triac	=2N6342: 400V	17j		T2802D, MAC222-6, TIC226D, TXD10K40,++
2N6343A	Triac	=2N6343: 12A(Tc=80°)	17j		TIC236D, TW11N400, TXD10K40P, MAC15-6,++
2N6344	Triac	=2N6342: 600V	17j		T2802M, MAC222-6, TIC226M, TXD10K60,++
2N6344A	Triac	=2N6344: 12A(Tc=80°)	17j		TIC236M, TW11N600, TXD10K60P, MAC15-8,++
2N6345	Triac	=2N6342: 600V	17j		T2802N, MAC222-10, TIC226N, TXD10K60,++
2N6345A	Triac	=2N6345 12A(Tc=60°)	17j		TIC236N, TW11N600, TXD10K60P, MAC15-10++
2N6346	Triac	200V, 8A(Tc=80°), Igt/Ih<75/<40mA	17j	Mot,Rca,Tix	TAG224-200, MAC222A-4, BT137/500,++
2N6346A	Triac	=2N6346: 12A(Tc=80°)	17j		BT138/500, TAG255-200, TXD10H40P,++
2N6347	Triac	=2N6346: 400V	17j		TAG224-400, MAC222A-6, BT137/500,++
2N6347A	Triac	=2N6347: 12A(Tc=80°)	17j		BT138/500, TAG255-400, TXD10H40P,++
2N6348	Triac	=2N6346: 600V	17j		TAG224-600, MAC222A-8, BT137/600,++
2N6348A	Triac	=2N6346: 12A(Tc=80°)	17j		BT138/600, TAG255-600, TXD10H60P,++
2N6349	Triac	=2N6346: 600V	17j		TAG224-600, MAC222A-10, BT137/800,++
2N6349A	Triac	=2N6349: 12A(Tc=80°)	17j		BT138/800, TAG255-800, TXD10H60P,++
2N635(A)	Ge-N	NF/S, 20..25V, 0,3A, 0,15W, 12MHz	2a(B=case)	USA	ASY26..29, ASY73..75
2N6350	Si-N-Darl	S, 80V, 5A, 5W(Tc=50°), B>2000	5	Amc,Stc,Uni	—
2N6351	Si-N-Darl	S, 150V, 5A, 5W(Tc=50°), B>1000	5	Amc,Stc,Uni	—
2N6352	Si-N-Darl	=2N6350: 25W	22/3-Pin	Amc,Stc,Uni	—
2N6353	Si-N-Darl	=2N6351: 25W	22/3-Pin	Amc,Stc,Uni	—
2N6354	Si-N	S-L, 150/120V, 10A, 140W, >80MHz	23a	USA,Rca,Sgs	—
2N6355	Si-N-Darl	NF/S-L, 50V, 20A, 150W, B>500	23a(A)	Ker,Mot,Stc	BDX69(A..C), 2N6282..84, MJ11012,++
2N6356	Si-N-Darl	=2N6355: B>1500	23a(A)		BDX69(A..C), 2N6282..84, MJ11012,++
2N6357	Si-N-Darl	=2N6355: 80V	23a(A)		BDX69A..C, 2N6283..84, MJ11014,++
2N6358	Si-N-Darl	=2N6355: 80V, B>1500	23a(A)		BDX69A..C, 2N6283..84, MJ11014,++
2N6359	Si-N	NF/S-L, 100V, 16A, 150W, >0,2MHz	23a	USA,Tix	BD317, BDX40, 2N3772, 2N5629..31,++
2N636(A)	Ge-N	NF/S, 20..25V, 0,3A, 0,15W, 17MHz	2a(B=case)	USA	ASY28..29, ASY73..75
2N6360	Si-N	=2N6359: 120V	23a		BDX50, 2N3773, 2N5630..31, 2SC2608,++
2N6361	Si-N	HF-L, 60V, 4A, 50W	57s	Ctr,Mot	—
2N6362	Si-N	HF-L, 80V, 6A, 110W	57s	Sol	—
2N6363	Si-N	HF-L, 50V, 10A, 175W	57s	Ctr,Mot	—
2N6364	Si-N	HF-L, 50V, 10A, 175W	57s	Ctr,Mot	—
2N6365(A)	Ge-P	HF, 30V, 0,1A, 0,15W, 500MHz	2a	Mot	—
2N6366	Si-N	HF-Tr/E, 36V, 1A, PEP=2,5W(30MHz)	49m	Mot	(MRF476)
2N6367	Si-N	AM-SSB-L, 36V, 2A, PEP=9W(30MHz)	59r	Mot	MRF433
2N6368	Si-N	AM-SSB-L, 40V, 6A, PEP=40W(30MHz)	59r	Mot	MRF460
2N6369	Si-N	HF-L, 80V, 15A, 220W	57s	Mot	—
2N637	Ge-P	NF/S-L, -/40V, 5A, 60W	23a	USA	AL102..103, AUY26, 2N1545..48,++
2N6370	Si-N	AM-SSB-L, 65V, 1,5A, PEP=10W(30MHz)	59r	Mot	MRF433
2N6371	Si-N	NF/S-L, 50V, 5A, 150W, >0,8MHz	23a	USA,Rca,Tix	BD315, BDX40, 2N3772, 2N5629..31,++
2N6372	Si-N	NF/S-L, 90V, 6A, 40W, >4MHz	22a	Rca,Ssi,Stc	BD243C, BD543C, BD801, 2N5429..30,++
2N6373	Si-N	=2N6372: 70V	22a		BD243B, BD543B, BD799, 2N5427..30,++
2N6374	Si-N	=2N6372: 50V	22a		BD243A, BD543A, BD797, 2N5427..30,++
2N6375	Si-N	S, 75V, 1,5A, 0,56W, <16/45ns	2a	Nsc	2N3737
2N6376	Si-N	=2N6375: 1W	2a		BSS14, 2N3735, 2N5262, 2N5859..61
2N6377	Si-P	S-L, 100V, 50A, 250W, >30MHz	23a	Kar,Mot,Stc	—
2N6378	Si-P	=2N6377: 120V	23a		—
2N6379	Si-P	=2N6377: 140V	23a		—
2N637A	Ge-P	=2N637: -/70V	23a		AL102..103, AUY26, 2N1546..48,++
2N637B	Ge-P	=2N637: -/80V	23a		AL102..103, AUY28, 2N1547..48,++
2N638	Ge-P	NF/S-L, -/40V, 5A, 60W	23a	USA	AL102..103, AUY28, 2N1545+F15656..48,++
2N6380	Si-P	=2N6377:	49m		—
2N6381	Si-P	=2N6377: 120V	49m		—
2N6382	Si-P	=2N6377: 140V	49m		—
2N6383	Si-N-Darl+Di	NF/S-L, 40V, 10A, 100W, >20MHz	23a(A)	Fch,Fer,Lbd	BDV67, BDW63, BDX63, BDX65,++
2N6383	Si-N-Darl+Di			Mot,Rca,Stc	—
2N6384	Si-N-Darl+Di	=2N6383: 80V	23a(A)		BDV67, BDW83A, BDX83A, BDX85A,++
2N6385	Si-N-Darl+Di	=2N6383: 80V	23a(A)		BDV67A, BDW63B, BDX83B, BDX85B,++
2N6386	Si-N-Darl+Di	NF/S-L, 40V, 8A, 65W, B>1000	17c(A)	Fch,Mot,Nsc	BD643, BD895, BDW73, BDX53,++
2N6386	Si-N-Darl+Di			Rca,Sgs,Sol	—
2N6387	Si-N-Darl+Di	=2N6386: 80V, 10A	17c(A)		BD845, BD697, BDW73A, BDX53A,++
2N6388	Si-N-Darl+Di	=2N6386: 80V, 10A	17c(A)		BD847, BD699, BDW73B, BDX53B,++
2N6389	Si-N	UHF, 20V, 0,04A, 0,2W, >1GHz	5g	Rca,Sca	BF377..376, BFR37, BFW30, BFX73,++
2N638A	Ge-P	=2N638: -/70V	23a		AL102..103, AUY26, 2N1548..46,++
2N638B	Ge-P	=2N638: -/80V	23a		AL102..103, AUY26, 2N1547..48,++
2N639	Ge-P	NF/S-L, -/40V, 5A, 80W	23a	USA	AL102..103, AUY28, 2N1545..48,++

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2N6390	Si-N	HF-L, 50V, 1A, 8,3W	62a	Rca	—
2N6391	Si-N	HF-L, 50V, 2,5A, 16W	62a	Rca	—
2N6392	Si-N	HF-L, 50V, 3,5A, 21W	62a	Rca	—
2N6393	Si-N	HF-L, 45V, 3,5A, 21W	62a	Rca	—
2N6394	50Hz-Thy	50V, 12A(Tc=90°), Igt/Ih<30/<40mA	17e	Mot,Rca,Tag	TAG665-100, TIC126F, T7,5N400, 2N6400,++
2N6395	50Hz-Thy	=2N6394: 100V	17e		TAG665-100, TIC126A, T7,5N400, 2N6401,++
2N6396	50Hz-Thy	=2N6394: 200V	17e		TAG665-200, TIC126B, T7,5N400, 2N6402,++
2N6397	50Hz-Thy	=2N6394: 400V	17e		TAG665-400, TIC126D, T7,5N400, 2N6403,++
2N6398	50Hz-Thy	=2N6394: 600V	17e		TAG665-600, TIC126M, T7,5N600, 2N6404,++
2N6399	50Hz-Thy	=2N6394: 800V	17e		TAG665-600, TIC126N, T7,5N800, 2N6405,++
2N639A	Ge-P	=2N639: -/70V	23a		AL102..103, AUY28, 2N1546..48,++
2N639B	Ge-P	=2N639: -/80V	23a		AL102..103, AUY28, 2N1547..48,++
2N54	Ge-P	NF, 25V, 0,02A, 0,1W	2a	USA	AC126..126, AC151
2N640	Ge-P	HF, 34V, 10mA, 0,08W, 42MHz	1g	Rca, Sty	AF124..126, AF200
2N6400	50Hz-Thy	50V, 16A(Tc=90°), Igt/Ih<30/<40mA	17e	Mot,Rca,Tag	TAG660-100, TAG661-100, T9,5N400, ++
2N6401	50Hz-Thy	=2N6400: 100V	17e		TAG680-100, TAG661-100, T9,5N400,++
2N6402	50Hz-Thy	=2N6400: 200V	17e		TAG660-200, TAG661-200, T9,5N400,++
2N6403	50Hz-Thy	=2N6400: 400V	17e		TAG680-400, TAG681-400, T9,5N400,++
2N6404	50Hz-Thy	=2N6400: 800V	17e		TAG680-800, TAG681-600, T9,5N600,++
2N6405	50Hz-Thy	=2N6400: 800V	17e		TAG680-600, TAG681-800, T9,5N600,++
2N6406	Si-P	NF/S-L, 80V, 2A, 12,5W, >50MHz	14j	Mot	(BD376, BD788, BD790, 2SB674..675,++)
2N6407	Si-P	=2N6407: 100V	14j		(BD380, BD782, 2SB674..675,++)
2N6406	Si-N	NF/S-L, 80V, 2A, 12,5W, >50MHz	14j	Mot	(BD377, BD787, BD769, 2SD1177..78,++)
2N6409	Si-N	=2N6406: 100V	14j		(BD379, BD791, 2SD1177..1178,++)
2N641	Ge-P	HF, 34V, 10mA, 0,08W, 42MHz	1g	Rca,Sty	AF124..126, AF200
2N6410	Si-N	NF/S-L, 40V, 4A, 15W, >50MHz	14j	Mol	(BD785, MJE240..244, 2SD1346,++)
2N6411	Si-P	NF/S-L, 40V, 4A, 15W, >50MHz	14j	Mot	(BD786, MJE250..254, 2SB986,++)
2N6412	Si-N	NF/S-L, 60V, 4A, 15W, >50MHz	14j	Mol	(BD785, MJE240..244, 2SD1348,++)
2N6413	Si-N	=2N6412: 80V	14j		(BD787, BD789, MJE240..244,++)
2N6414	Si-P	NF/S-L, 80V, 4A, 15W, >50MHz	14j	Mot	(BD786, MJE250..254, 2SB986,++)
2N6415	Si-P	=2N6414: 80V	14j		(BD788, BD790, MJE250..254,++)
2N6416	Si-N	NF/S-L, 80V, 3A, 15W, >40MHz	14j	Mol	(BD787, BD789, MJE240..244,++)
2N6417	Si-N	=2N6416: 100V	14j		(BD791, BDX35..37, MJE243..244,++)
2N6418	Si-P	NF/S-L, 80V, 3A, 15W, >40MHz	14j	Mot	(BD788, BD790, MJE250..254,++)
2N6419	Si-P	=2N6418: 100V	14j		(BD792, MJE253. 254)
2N642	Ge-P	HF, 34V, 10mA, 0,06W, 42MHz	1g	Rca,Sty	AF124..126, AF200
2N6420	Si-P	S-L, 250/175V, 1A, 35W, >10MHz	22e	Mot,Rca	BUX66A .C, 2N5344..45, 2SA1009(A),++
2N6421	Si-P	S-L, 375/250V, 1A, 35W, >10MHz	22a	Mot,Rca	BUX66C, 2N6213..14, 2SA1009A++
2N6422	Si-P	S-L, 500/300V, 2A35W, >10MHz	22a	Mot,Rca	—
2N6423	Si-P	S-L, 500/300V, 2A, 35W, >15MHz	22a	Mot,Rca	—
2N6424	Si-P	S-L, 250/225V, 1A, 20W, >10MHz	22a	Mot	BUX66A .C, 2N5344..45, 26A1009(A),++
2N6425	Si-P	S-L, 325/300V, 1A, 20W, >10MHz	22e	Mot	BUX88B..C, 2N6212..14, 2SA1009(A),++
2N6426	Si-N-Darl	Uni, 100V, 0,5A, 0,625W, B>20000	5e	Mot,Nsc,Spr	BC517, BC617, MPS-A25..29, 2SD892A++
2N6427	Si-N-Darl	Uni, 100V, 0,5A, 0,625W, B>10000	5e		BC517, BC617, MPS-A25..29, 2SD892A,++
2N6426(A)	Si-N	Uni, 80V, 0,2A 0,625W, >100MHz	7e	Mot	BC414, BC550, 2SC1775(A), 2SC2390,++
2N6429(A)	Si-N	Uni, 55V, 0,2A, 0,625W, >700MHz	7e		BC414, BC550, 2SC1775(A), 2SC2390,++
2N643	Ge-P	HF/S, 30V, 0,1A, 0,12W, 30MHz	2a	Rca,Sty	2N2955..57
2N6430	Si-N	Vid, 200V, 0,5A, 0,5W, >50MHz	2e	Mot	BF391..393, BFP22, MPS-A42..43,++
2N6431	Si-N	=2N6430: 300V	2a		BF393, BFP25, MPS-A42, 2SD1350
2N6432	Si-P	Vid, 200V, 0,5A, 0,5W, >50MHz	2a	Mot	BF491..493, BFP23, MPS-A92..93,++
2N6433	Si-P	=2N6432: 300V	2a		BF493, BFP26, MPS-A92, 2SB1074
2N6436	Si-P	S-L, 100V, 25A, 200W, >40MHz	23a	Ker,Mot,Stc	2N6377..79
2N6437	Si-P	=2N6436: 120V	23a		2N6378..79
2N6436	Si-P	=2N6436: 140V	23a		2N6379
2N6439	Si-N	VHF/UHF-L, 80V, PQ=60W(400MHz)	57s	Mot	MRF327, 2SC2186, 2SC2796
2N644	Ge-P	HF/S, 30V, 0,1A, 0,12W, 50MHz	2a	Rca,Sty	2N2955..57
2N6441	Si-N	Dual, 80V, 0,01A, 0,55W, >180MHz	TO-77	Mot,+E6010si	2N3409..11
2N6442	Si-N	Dual, 80V, 0,01A, 0,55W, >160MHz	TO-77		2N3409..11
2N6443	Si-N	Dual, 80V, 0,01A, 0,55W, >180MHz	TO-77		2N3409..11
2N6444	Si-N	Dual, 60V, 0,01A, 0,55W, >160MHz	TO-77		2N3409..11
2N6445	Si-N	Dual, 60V, 0,01A, 0,55W, >160MHz	TO-77		2N3409..11
2N6446	Si-N	Dual, 80V, 0,01A, 0,55W, >160MHz	TO-77		2N3409..11
2N6447	Si-N	Dual, 60V, 0,01A, 0,55W, >160MHz	TO-77		2N3409..11
2N6448	Si-N	Dual, 80V, 0,01A, 0,55W, >160MHz	TO-77		2N3409..11
2N6449	N-FET	Uni, 300V, Idss>2mA, Up<15V	2b	Tdy,Tix	—
2N645	Ge-P	HF/S, 30V, 0,1A, 0,12W, 75MHz	2a	Rca,Sty	2N2955..57

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2N6450	N-FET	Uni, 200V, Idss>2mA, Up<15V	2b	Tdy,Tix	—
2N6451	N-FET	Uni, ra, 20V, Idss>5mA, Up<3,5V	5k	Tix	BC264, BF410C, 2SK147, 2SK168
2N6452	N-FET	Uni, ra, 25V, Idss>5mA, Up<3,5V	5k	Tix	BC264, BF410C, 2SK147, 2SK168
2N6453	N-FET	Uni, ra, 20V, Idss>15mA, Up<5V	5k	Tix	BF256B, BF348, BFT10A,B, 2N5397
2N6454	N-FET	Uni, ra, 25V, Idss>15mA, Up<5V	5k	Tix	BF256B, BF348, BFT10A,B, 2N5397
2N6455	Si-N	HF-L, 45V, 7A, 60W, >75MHz	56r	Ppc	—
2N6456	Si-N	HF-L, 45V, 12A, 75W, >60MHz	55r	Ppc	—
2N6457	Si-N	HF-L, 45V, 20A, 140W, >50MHz	55r	Ppc	—
2N6456	Si-N	HF-L, 45V, 7A, 75W, >75MHz	59r	Ppc	—
2N6459	Si-N	HF-L, 45V, 12A, 120W, >60MHz	59r	Ppc	—
2N646	Ge-N	NF/S, 25V, 0,05A, 0,1W	1a	Sty	AC127, ASY26..29
2N6460	Si-N	HF-L, 45V, 20A, 140W, >50MHz	59r	Ppc	—
2N6461	Si-N	Vid, 300V, 0,1A, 1W, >200MHz, B>30	2a	Ssi,Tix	BF259, BF659, BFS89, 3N5058
2N6462	Si-N	=2N6461: B>100	2a		BF259, BF659, BFS89, 3N5058
2N6463	Si-N	=2N6461: 250V	2a		BF256..259, BF659..659, 2N5058..59,++
2N6464	Si-N	=2N6461: 250V, B>100	2a		BF256..259, BF656..659, 2N5056..59,++
2N6465	Si-N	NF/S-L, 110V, 4A, 40W, >5MHz	22a	Ker,Stc,Stc	BD243C, BD539D, BD955, 2SD961,++
2N6468	Si-N	=2N6465: 130V	22a		BD243D, 2SC2516, 2SD961
2N6467	Si-P	NF/S-L, 110V, 4A, 40W, >5MHz	22a	Ker,Rca,Stc	BD244C, BD540D, BD956, 2SB869,++
2N6468	Si-P	=2N6467: 130V	22a		BD244D, 2SB869
2N6459	Si-P	NF/S-L, 50V, 15A, 125W, >10MHz	23a	USA,Rca,Tix	BD316, BD546A, MJ2955, 2N5879..60,++
2N647(/22)	Ge-N	NF/S, 25V, 0,05A, 0,1..0,18W	2a	Csr,Etc,Syl	AC127, ASY26..29
2N6470	Si-N	NF/S-L, 50V, 15A, 125W, >5MHz	23a	USA,Rca,Tix	BD315, BD545A, 2N3055, 2N5861..82,++
2N6471	Si-N	=2N6470: 70V	23a		BD315, BD545B, 2N3055, 2N5881..62,++
2N6472	Si-N	=2N6470: 90V	23a		BD317, BD545C, 2N3055, 2N5882,++
2N6473	Si-N	=2N6465:	17j	USA,Nsc,Rca	→2N6465
2N6474	Si-N	=2N6468;	17j	USA,Nsc,Rca	→2N6466
2N6475	Si-P	=2N6467:	17j	USA,Nsc,Rca	→2N6467
2N6478	Si-P	=2N6468:	17j	USA,Nsc,Rca	→2N6466
2N6477	Si-N	NF/S-L, 140V, 2,5A, 50W, >0,2MHz	17j	Rca	BD241D, BD941, 2SC2518
2N6478(A)	Si-N	=2N6477: 160V	17j		BD241D
2N6479	Si-N	S-L, RadH, 100/60V, 12A, 87W, >100MHz		Rca	—
2N6460	Si-N	=2N6479: RadH, 100/60V		Rca	—
2N6481	Si-N	=2N6479: RadH, 117W		Rca	—
2N6462	Si-N	=2N6479: RadH, 100/60V, 117W		Rca	—
2N6463	N-FET	Dual, 50V, Idss>0,5mA, Up<4V	TO-71	Isi,Nsc,Sol	—
2N6484	N-FET	Dual, 50V, Idss>0,5mA, Up<4V	TO-7		—
2N6485	N-FET	Dual, 50V, Idss>0,5mA, Up<4V	TO-7		—
2N6486	Si-N	NF/S-L, 50V, 15A, 75W, >5MHz	17j	Fch,Mot,Nsc	BD743A, BD907, BDT81
2N6468	Si-N			Rca,Sgs	—
2N6487	Si-N	=2N6486: 70V	17j		BD743B, BD909, BDT63
2N6468	Si-N	=2N6486: 90V	17j		BD743C, BD911, BDT65
2N6489	Si-P	NF/S-L, 50V, 15A, 75W, >5MHz	17j	=2N6486	BD744A, BD908, BDT62
2N649(/5,/22)	Ge-N	NF/S, 20V, 0,05A, 0,1..0,18W	2a	USA	AC127, ASY26..29
2N6490	Si-P	=2N648 9 70V	17j		BD744B, BD910, BDT84
2N6491	Si-P	=2N6489: 90V	17j		BD744C, BD912, BDT86
2N6492	Si-N-Darl	NF/S-L, 80V, 8A, 100W, B>500	23a(A)	Mol	BDV67, BDW83A, BDX67, MJ4033,++
2N6493	Si-N-Darl	NF/S-L, 100V, 6A, 100W, B>500	23a(A)	Mot	BDV67A, BDW83C, BDX67B, MJ4035,++
2N6494	Si-N-Darl	NF/S-L, 100V, 8A, 100W, B>500	23a(A)	Mot	BDV67A, BDW83C, BDX67B, MJ4035,++
2N6495	Si-N	S-L, 150V, 10A, 70W, >25MHz	22a	USA,Mot,Tix	BUS36..37, BUV27(A), 2SC2867
2N6496	Si-N	S-L, 150V, 15A, 140W, >60MHz	23a	Ker,Rcs,Sgs	BUW57..68, BUX41, 2SD552, 2SD583,++
2N8496	Si-N			Stc,Tix,Unl	—
2N6497	Si-N	NF/S-L, 350/250V, 5A, 80W, >5MHz	17j	Mot,Sgs	BUT56(A), MJE51T..53T, 2SC2907,++
2N6498	Si-N	=2N6497: 400/300V	17j		BUT56(A), MJE52T..53T, 2SC2907,++
2N6499	Si-N	=2N6497: 450/350V	17j		BUT56(A), MJE53T, 2SC3056,++
2N65	Ge-P	NF, 25V, 0,02A, 0,125W	2a	USA	AC125..126, AC151
2N650(A)	Ge-P	NF/S, 45V, 0,5A, 0,2W, B>33	2a	USA, Mol	2N1189..90, 2SB4059T
2N6500	Si-N	S-L, 120V, 4A, 35W, >60MHz	22a	USA,Rca,Tix	BDV10..12, BUX77, 2SC2767, 2SD772,++
2N6501	Si-N	4xNPN, 60V, 1A, 0,6W, >250MHz	14-FLT	Mot	—
2N6502	Si-N	Dual, 80V, 1A, 0,6W, >250MHz	TO-77	Mot,Sgs	—
2N6503	Si-N	Dual, 60V, 1A, 0,35W, >250MHz	10-FLT	Mot,Sgs	—
2N6504	50Hz-Thy	50V, 25A, Igt/Ih<40/<40mA	17a	Mot	MCR69-2
2N6505	50Hz-Thy	=2N6504: 100V	17a		MCR69-3
2N6506	50Hz-Thy	=2N6504: 200V	17a		—
2N6507	50Hz-Thy	=2N6504: 400V	17e		—
2N6506	50Hz-Thy	=2N6504: 600V	17a		—

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2N6509	50Hz-Thy	=2N6504: 800V	17e		—
2N651(A)	Ge-P	=2N650; B>45	2a	USA, Mot	2N1189..90, 2SB405ST
2N6510	Si-N	S-L, 250/200V, 7A, 120W, >3MHz	23a	USA, Rca	BUX18(A..C), BUX43..44, 2SC3041, ++
2N6511	Si-N	=2N6510: 300/250V	23a		BUX18(A..C), BUX43..44, 2SC3041, ++
2N6512	Si-N	=2N6510: 350/300V	23a		BUX18(A..C), BUX43..44, 2SC3041, ++
2N6513	Si-N	=2N6510: 400/350V	23a		BUX18(B..C), BUX43..44, 2SC3041, ++
2N6514	Si-N	=2N6510: 350/300V	23a		BUX18(A..C), BUX43..44, 2SC3041, ++
2N6515	Si-N	NF/S/Vid, 250V, 0,5A, 0,625W, >40MHz	7a	Mot, Sam	BF392..393, BFP25, MPS-A42, 2SD1350
2N6516	Si-N	=2N6515: 300V	7e	Mot, Sam	BF393, BFP25, MPS-A42, 2SD1350
2N6517	Si-N	=2N6515: 350V	7a	Mot, Sam	2SD1350
2N6518	Si-P	NF/S/Vid, 250V, 0,5A, 0,625W, >40MHz	7e	Mot, Sam	BF492..493, BFP26, MPS-A92, 2SB1074
2N6519	Si-P	=2N6518: 300V	7e	Mot, Sam	BF493, BFP26, MPS-A92, 2SB1074
2N652(A)	Ge-P	=2N650: B>80	2a	USA, Mot	2N1189..90, 2SB405ST
2N6520	Si-P	=2N6518: 350V	7e	Mot, Sam	BF493S, 2SB1074
2N6521	Si-P-Darl	80V, 1A, 0,7W, B>10000	5	Mot	—
2N6522	Si-P-Darl	=2N6521: B>20000	5		—
2N6523	Si-N	HF-L, 40V, 0,6A, 5W	62a	Mws	—
2N6524	Si-N	HF-L, 40V, 1,2A, 10W	62a	Mws	—
2N6525	Si-N	HF-L, 40V, 2,5A, 20W	62a	Mws	—
2N6526	Si-N	HF-L, 50V, 0,5A, 3,9W	62a	Mws	—
2N6527	Si-N	HF-L, 50V, 1A, 5W	82a	Mws	—
2N6528	Si-N	HF-L, 50V, 1,2A, 10W	82a	Mws	—
2N6529	Si-N	HF-L, 50V, 2,5A, 20W	82a	Mws	—
2N653	Ge-P	NF/S, 30V, 0,25A, 0,2W, β>30	2a	USA, Mot	AC125..126, AC151
2N6530	Si-N-Darl+Di	NF/S-L, 80V, 8A, 65W, B>1000	17c(A)	Rca	BD647, BD899, BDX53B, BDX73B, ++
2N6531	Si-N-Darl+Di	NF/S-L, 100V, 8A, 65W, B>500	17c(A)	Rca	BD849, BD901, BDX53C, BDX73C, ++
2N6532	Si-N-Darl+Di	NF/S-L, 100V, 8A, 65W, B>1000	17c(A)	Rca	BD849, BD901, BDX53C, BDX73C, ++
2N6533	Si-N-Darl+Di	NF/S-L, 120V, 8A, 65W, B>1000	17c(A)	Rca	BD651, BDT21, BDX53D, BDX73D, ++
2N6534	Si-N-Darl+Di	=2N6530: 36W	17c(A)	Rca	→2N6530
2N6535	Si-N-Darl+Di	=2N6531: 36W	17c(A)	Rca	→2N6531
2N6536	Si-N-Darl+Di	=2N6532: 36W	17c(A)	Rca	→2N6532
2N6537	Si-N-Darl+Di	=2N6533: 36W	17c(A)	Rca	→2N6532
2N6538	Si-N	Uni, ra, 80V, 0,2A, 0,625W, >200MHz	7a	Tix	BC414, BC650, 2SC2240, 2SC2459, ++
2N6539	Si-N	Uni, ra, 80V, 0,2A, 0,625W, >200MHz	7a	Tix	BC414, BC650, 2SC2240, 2SC2459, ++
2N654	Ge-P	=2N653: β>50	2a	USA, Mot	AC125..126, AC151
2N6540	Si-N	Uni, ra, 80V, 0,2A, 0,625W, >200MHz	7a		2SC1775(A), 2SC2240, 2SC2459, 2SC2390, ++
2N6541	Si-N	Uni, ra, 80V, 0,2A, 0,625W, >200MHz	7a		2SC1775(A), 2SC2240, 2SC2459, 2SC2390, ++
2N6542	Si-N	S-L, 650/300V, 5A, 100W, >6MHz	23a	USA, Mot, Rca	BUS11(A), BUX62..83, 2SC3048, ++
2N6542	Si-N			Sgs, Tix, Tos	—
2N6543	Si-N	=2N6542: 850/400V	23a		BUS11(A), BUX82..83, 2SC3048, ++
2N6544	Si-N	S-L, 650/300V, 8A, 125W, >6MHz	23a	=2N6542	BUS12(A), BUX47(A), 2SC3092, 2SD811, ++
2N6545	Si-N	=2N6544: 650/400V	23a		BUS12(A), BUX47(A), 2SC3092, 2SD811, ++
2N6546	Si-N	S-L, 650/300V, 15A, 175W, >6MHz	23a	=2N6542	BUS13(A), BUS97(A), BUX47(A..C), ++
2N6547	Si-N	=2N6546: 650/400V	23a		BUS13(A), BUS97(A), BUX47(A..C), ++
2N6548	Si-N-Darl	NF/S-L, 50V, 2A, 10W, B>25000	13m(C)	Mot, Nsc	BD411..412, MPS-U45
2N6549	Si-N-Darl	=2N6548: B>15000	13m(C)		BD411..412, MPS-U45
2N655	Ge-P	=2N653: β+C15851>100	2a	USA, Mot	AC125..126, AC151
2N6550	N-FET	Uni, 20V, Idss=10..250mA, Up<3V	2f	Tdy	—
2N6551	Si-N	NF/S-L, 60V, 1A, 10W, >75MHz	13m	Mot, Nsc	BC366, BD415, BD517, BD525, ++
2N6552	Si-N	=2N6551: 80V	13m		BC367, BD417, BD519, BD527, ++
2N6553	Si-N	=2N6551: 100V	13m		BD419, BD529
2N6554	Si-P	NF/S-L, 80V, 1A, 10W, >75MHz	13m	Mot, Nsc	BC363, BD416, BD518, BD526, ++
2N6555	Si-P	=2N6554: 80V	13m		BC364, BD418, BD520, BD528, ++
2N6556	Si-P	=2N6554: 100V	13m		BD420, BD530
2N6557	Si-N	Vid-L, 250V, 0,5A, 10W, >45MHz	13m	Mot	BF381..382, BF480..462, MPS-U10
2N6558	Si-N	=2N6557: 300V	13m		BF382, BF461..462, BF468, MPS-U10
2N6559	Si-N	=2N6557: 350V	13m		BF462
2N656(A,S)	Ge-P	NF/S, 80V, 0,5A, 1W	2a	USA, Mot, Tix	BC140..141, BC300..302, 2N3053, ++
2N6560	Si-N	S-L, 450/450V, 10A, 220W, >10MHz	23a	Sol, Stc	—
2N6561	Si-N	=2N6560: 300/300V	23a		—
2N6562	Si-N	=2N6560: 175W	49a		2N6689..93
2N6563	Si-N	=2N6560: 300/300V, 175W	49a		2N6689..93
2N6564	50Hz-Thy	300V, 0,5A(Tc=55°), Igt/Ih<0,2/<5mA	7n	Gen, Tag	2N5064, TAG72D, TAG59D, 2N6683, ++
2N6565	50Hz-Thy	=2N6564: 400V	7n		TAG72D, TAG59D, 2N6683, (BT149D, ++)
2N6566	Si-N	S, Chopper, 30/30/30V, 0,1A, 0,4W	2a	Tdy	—
2N6567	Si-P	S, Chopper, 30/30/30V, 0,1A, 0,4W	2a	Tdy	—

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2N6568	N-FET	Uni, 30V, Idss>500mA, Up<10V	2b	Tdy	—
2N6569	Si-N	NF/S-L, 45V, 12A, 100W, >1,5MHz	23a	Fch,Mot,Rca	BD315, BD545A, BDW51, 2N5881..82,++
2N6569	Si-N			Tix	—
2N657(A,S)	Ge-P	=2N656: 100V	2a	USA,Mot,Tix	BC141, BC300, 2N1889..90, 2N1990,++
2N6570	Si-N	NF/S-L, 100V, 40A, 250W, >1MHz	23a	Stc,Tw	2N6032..33, 2N6274..77
2N6571	Si-N	=2N6570: 115V	23a		2N6032..33, 2N6274..77
2N6572	Si-N	HF-L, 60V, 12A, 250W	57s	Ctr	—
2N6573	Si-N	S-L, 500/250V, 10A, 125W, 15MHz	23a	USA,Mot,Tho	BUW25..26, BUW34..36, 2SC3046,++
2N6574	Si-N	=2N6573: 600/275V	23a		BUW25..26, BUW35..36, 2SC3046,++
2N6575	Si-N	=2N6573: 700/300V	23a		BUS12(A), BUW26, BUW35..36, 2SC3046++
2N6576	Si-N-Darl+Di	NF/S-L, 60V, 15A, 120W, B>500	23a (A)	Lbd,Mot,Rca	BDV67, BDW83A, BDX67, MJ4033,++
2N6577	Si-N-Darl+Di	=2N6576: 90V	23a (A)		BDV67A, BDW83C, BDX67B, MJ4035,++
2N6578	Si-N-Darl+Di	=2N6576: 120V	23a (A)		BDV67B, BDW83D, BDX67C
2N6579	Si-N	S-L, 450/350V, 10A, 125W, >25MHz	23a	Am+E6937c	BUW24..26, BUW34..36, 2SC3046,++
2N658	Ge-P	NF/S, 25/16V, 1A, 0,2W	2a	USA	AC126, AC153, AC188, 2SB405,++
2N6580	Si-N	S-L, 500/400V, 10A, 125W, >25MHz	23a		BUW25..26, BUW34..36, 2SC3046,++
2N6581	Si-N	S-L, 550/450V, 10A, 125W, >25MHz	23a		BUW25..26, BUW35..36, 2SC3046,++
2N6582	Si-N	S-L, 450/350V, 10A, 125W, >25MHz	23a	Amc,Trw	BUW24..26, BUW34..36, 2SC3046,++
2N6583	Si-N	S-L, 500/400V, 10A, 125W, >25MHz	23a		BUW25..26, BUW34..36, 2SC3046,++
2N6564	Si-N	S-L, 550/450V, 10A, 125W, >25MHz	23a		BUW25..26, BUW35..36, 2SC3046,++
2N6585	Si-N	=2N6579:	49a		2N6689..93
2N6566	Si-N	=2N6560:	49a		2N6690, 2N6692..93
2N6567	Si-N	=2N6561:	49a		2N6690, 2N6692..93
2N6588	Si-N	=2N6582:	49a		2N6669..93
2N6569	Si-N	=2N6583:	49a		2N6690, 2N6692..93
2N659	Ge-P	NF/S, 25/14V, 1A, 0,2W	2a	USA	AC128, AC153, AC188, 2SB405,++
2N6590	Si-N	=2N6584:	49a		2N6690, 2N6692..93
2N6591	Si-N	S, HA-Tr, Reg, 150V, 0,5A, 10W, >35MHz	13m	Mot,Nsc	BF360..362, BF460..462, MPS-U10,++
2N6592	Si-N	=2N6591: 200V	13m		BF361..362, BF460..462, MPS-U10,++
2N6593	Si-N	=2N6591: 250V	13m		BF381..382, BF460..462, MPS-U10,++
2N6594	Si-P	NF/S-L, 45V, 12A, 100W, >2,5MHz	23a	Mot,Rca	BD316, BD546A, BDW52, 2N5879..80,++
2N6595	Si-N	UHF, ra, 20V, 25mA, 0,2W, >3,5GHz	5g	Amp	BFQ22, BFQ53, BFT66..67
2N6596	Si-N	UHF, ra, 15V, 25mA, 0,2W, >3,5GHz	5g	Amp	BFQ22, BFQ53, BFT66..67
2N6597	Si-N	UHF, ra, 20V, 25mA, 0,2W, >4GHz	5g	Amp	BFQ22, BFQ53, BFT88..67
2N6596	Si-N	UHF, ra, 15V, 25mA, 0,2W, >4GHz	5g	Amp	BFQ22, BFQ53, BFT66..67
2N6596	Si-N	UHF, ra, 20V, 75mA, 0,5W, >3GHz	5g	Amp	BFQ63, 2SC2570, 2SC3037, 2SC3337
2N88	Ge-P	NF/S-L, 60V, 0,6A, 27,5W		Wes	—
2N660	Ge-P	NF/S, 25/11V, 1A, 0,2W	2a	USA	AC128, AC153, AC188, 2SB405,++
2N6600	Si-N	UHF, ra, 20V, 75mA, 0,3W, >3,5GHz	5g	Amp	BFQ63, 2SC2570, 2SC3037, 2SC3337
2N6601	Si-N	UHF, ra, 20V, 50mA, 0,25W, >1GHz	5g	Amp	BFQ83, BFS55, 2SC2496
2N6602	Si-N	UHF, -/15V, 25mA, >3,5GHz	52r	Mot	BFQ59..60, BFQ72, BFT65, 2SC2844,++
2N6603	Si-N	UHF, 25V, 30mA, >3,5GHz	52r	Mot	BFQ59..60, BFQ72, BFT65, 2SC2844,++
2N6604	Si-N	UHF, 25V, 50mA, >3,5GHz	52r	Mot	BFQ72, BFT65, 2SC2844
2N6605	50Hz-Thy	30V, 0,275A(Ta=55°), Igt/Ih<0,2/<5mA	2a	Mot,Tag	TAG06Y, (TIC44, TIC60, MCR100-3,++)
2N6606	50Hz-Thy	=2N6605: 60V	2a		TAG06YY, (TIC48, TIC62, MCR100-3,++)
2N6607	50Hz-Thy	=2N6605: 100V	2a		TAG06A, (TIC48, TIC82, MCR100-3,++)
2N6606	50Hz-Thy	=2N6605: 200V	2a		TAG06B, (TIC47, TIC64, MCR100-4,++)
2N6609	Si-P	NF/S-L, 160/140V, 16A, 150W, >2MHz	23a	Mot,Rca	BD746F, MJ15016, 2SA1117
2N661	Ge-P	NF/S, 25/9V, 1A, 0,2W	2a	USA	AC128, AC153, AC188, 2SB405,++
2N6617	Si-N	UHF, -/18V, 10mA, 0,15W, 8GHz	51r	Hew	BFQ33, BFQ77, 2SC1948
2N8818	Si-N	UHF, 35V, 20mA, 0,3W(TG=125), 8GHz	51r	Hew,Mot	BFQ33, BFQ77, 2SC1948
2N6619	Si-N	=BFR35A		Sie	→BFR35A
2N662	Ge-P	NF/S, 25/10V, 1A, 0,2W	2a	USA	AC128, AC153, AC188, 2SB405,++
2N9620	Si-N	=BFR34A		Sie	→BFR34A
2N6621	Si-N	=BFW92		Sie	→BFW92
2N6622	Si-N	S-L, 600V, 10A, 45W(Tc=100°), >4MHz	23a	Amp	BUS12(A), BUW26, BUW35..36, BUX81,++
2N663	Ge-P	NF/S-L, 50V, 4A, 35W	23a	USA	AD149, AUY19..20, 2N1529..48
2N6648	Si-P-Darl+Di	NF/S-L, 40V, 10A, 100W, B>1000	23a(B)	Mot,Rca	BDV64, BDX84, BDX86, MJ2500,++
2N6649	Si-P-Darl+Di	=2N6648: 60V	23a(B)		BDV64, BDX84A, BDX86A, MJ2500,++
2N665	Ge-P	NF/S-L, 80V, 3A, 35W	23a	USA,Mot	AL102..103, AUY20, 2N2141, 2N2146,++
2N6650	Si-P-Darl+Di	=2N6646: 60V	23a(B)		BDV64A, BDX64B, BDX86B, MJ2501,++
2N6653	Si-N	S-L, 350/300V, 20A, 150W, >25MHz	23a	Gsi,Stc	BUV24, BUX24, 2SC3085
2N6654	Si-N	=2N6653: 400/350V	23a		BUV24, BUX24, 2SC3085
2N6655	Si-N	=2N6653: 450/400V	23a		BUV24, BUX24, 2SC3085
2N6656	MOS-N-FET-e	V-MOS, 35V, 2A, 25W, <1,8Ω, <10/10ns	23a	Sgs,Six	BUZ63, 2SK259..260
2N6657	MOS-N-FET-e	V-MOS, 60V, 2A, 25W, <3Ω, <10/10ns	23a	Sgs,Six	BUZ62, 2SK259..260

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2N6658	MOS-N-FET-e	V-MOS, 90V, 2A, 25W, <4Ω, <10/10ns	23a	Sgs,Six	BUZ63, 2SK259..260
2N6659	MOS-N-FET-e	S-L, 35V, 2A, 6,2W(Tc=25°), <1,8Ω(1A)	2a	Mot,Phi,Sgs	—
2N6659	MOS-N-FET-e			Six	—
2N6660	MOS-N-FET-e	S-L, 60V, 2A, 6,2W(Tc=25°), <3Ω(A)	2a	=2N6659	—
2N6661	MOS-N-FET-e	S-L, 90V, 2A, 6,2W(Tc=25°), <4Ω(1A)	2a		—
2N6665	Si-N	UHF, ra, 20V, 0,125A, 0,45W, 2GHz	5g	Miv	2SC2408, (BFR95)
2N6666	Si-P-Darl+Di	NF/S-L, 40V, 8A, 65W, B>1000	17c	Mot,Rca	BD644, BD896, BDW74, BDX54, ++
2N6667	Si-P-Darl+Di	=2N6666: 60V	17c		BD646, BD898, BDW74A, BDX54A, ++
2N6666	Si-P-Darl+Di	=2N6666: 60V	17c		BD648, BD900, BDW74B, BDX54B, ++
2N6669	Si-N	NF/S-L, 40V, 10A, 40W, >10MHz	17j	Rca	BD705, BD743, BD805, BD805, ++
2N6670	Si-N	AM-L, 80V, 1,5A, PQ=5W(40MHz)	13m	Rca	—
2N6671	Si-N	S-L, 450/300V, 5A, 150W, >15MHz	23a	Fer,Rca,Tho	BUW24..26, BUW34..36, BUW72, ++
2N6672	Si-N	=2N6671: 550/350V	23a		BUW25..26, BUW35..36, BUX60, ++
2N6673	Si-N	=2N6671: 650/400V	23a		BUW26, BUW35..35, BUX80..81, ++
2N6674	Si-N	S-L, 450/300V, 10A, 175W, >15MHz	23a	Fer,Rca,Tho	BUV25, BUW44, BUW75, BUX25, ++
2N6675	Si-N	=2N6674: 650/400V	23a		BUS13(A), BUW44..46, BUX46(A..C), ++
2N6676	Si-N	S-L, 450/300V, 15A, 175W, >15MHz	23a	USA,Mot,Thc	BUV25, BUW44..46, BUX25, BUX48, ++
2N6677	Si-N	=2N6676: 550/350V	23a		BUS13(A), BUW45..46, BUX48A..C), ++
2N6678	Si-N	=2N6676: 650/400V	23a		BUS13(A), BUW45..46, BUX48A..C), ++
2N6679	Si-N	UHF, 30V, 70mA, >4GHz	52r	Mot	BFQ82, BFQ198, 2SC3603
2N6681	60Hz-Thy	100V, 1A, Igt/Ih<0,2/<5mA	7n	Tho,Uni	TAG59A, BT149A, MCR606-3
2N6682	50Hz-Thy	=2N6681: 200V	7n		TAG59B, BT149B, MCR606-4
2N6663	50Hz-Thy	=2N6681: 400V	7a		TAG59D, BT149D, MCR606-6
2N6664	50Hz-Thy	=2N6661: 600V	7n		TAG59M, BT149M, MCR606-8
2N6685	50Hz-Thy	=2N6681: 800V	7n		(TAG615-800)
2N6666	Si-N	S-L, 260/180V, 25A, 200W, >20MHz	23a	Fer,Rca	BUV12, BUW73, BUX12
2N6667	Si-N	=2N6666: 280/180V	23a		BUV12, BUW73, BUX12
2N6688	Si-N	=2N6666: 300/200V, 20A	23a		BUV12, BUW73, BUX12
2N6689	Si-N	S-L, 450/300V, 15A, 175W, >15MHz	49a	Rca	—
2N669	Ge-P	NF/S-L, 40V, 3A, 90W	23a	USA,Mot	2N1529..1546, 2N3611..18
2N6690	Si-N	=2N6669: 650/400V	49a		—
2N6691	Si-N	S-L, 450/300V, 15A, 175W, >15MHz	49a	Rca	—
2N6692	Si-N	=2N6691: 550/350V	49a		—
2N6693	Si-N	=2N6691: 650/400V	49a		—
2N67	Ge-P	0,05A, 0,1W		Wes	—
2N670	Ge-P	NF/S, Chopper, 40/40/40V, 2A, 0,3W	2a	Spe,Ssi	—
2N6702	Si-N	S-L, 140/90V, 7A, 50W, >50MHz	17j	Rca,Sgs	BU409, BUW64A..C, TIP150..152, ++
2N6703+A15975	Si-N	=2N6702: 160/110V	17j		BU409, BUW64C, TIP150..152, ++
2N6704	Si-N	=2N6702: 160/130V	17j		BU409, BUW64C, TIP150..152, ++
2N6705	Si-N	Uni, 60V, 1A, 1,2W, >50MHz	30c	Gen,Nsc	2SD1281..82, (BD517, BD525, ++)
2N6706	Si-N	=2N6705: 60V	30c		2SD1281..82, (BD519, BD527, ++)
2N6707	Si-N	=2N6705: 100V	30c		2SD1281..82, (BD529)
2N6706	Si-P	Uni, 60V, 1A, 1,2W, >50MHz	30c	Gen,Nsc	2SB957..958, (BD518, BD526, ++)
2N6709	Si-P	=2N6706: 60V	30c		2SB957..956, (BD520, BD528, ++)
2N671	Ge-P	=2N670: 1W	2a	Spe,Ssi	—
2N6710	Si-P	=2N6708: 100V	30c		2SB957..958, (BD530)
2N6711	Si-N	Vid, 160V, 0,1A, 1,2W, 50MHz	30c	Gen,Nsc	(BF360..382, BF460..462, BF757..759)
2N6712	Si-N	=2N6711: 250V	30c		(BF361..382, BF460..462, BF757..759)
2N6713	Si-N	=2N6711: 300V	30c		(BF362, BF461..462, BF758..759)
2N6714	Si-N	Uni, 40V, 2A, 1,2W, >50MHz	30e	Gen,Nsc	2SD1078..79, (BD509, BD517, ++)
2N6715	Si-N	=2N6714: 50V	30e		2SD1078..79, (BD509, BD517, ++)
2N6716	Si-N	Uni, 60V, 2A, 1,2W, >50MHz	30e	Gen,Nsc	2SD1261..82, (BD517, BD525, ++)
2N6717	Si-N	=2N6716: 80V	30e		2SD1281..82, (BD519, BD527, ++)
2N6716	Si-N	=2N6716: 100V	30e		2SD1261..62, (BD529)
2N6719	Si-N	S/Vid, 300V, 0,1A, 1,2W, >30MHz	30e	Gen,Nsc	2SC2870, 2SC2924, 2SC3406, (BF617, ++)
2N672	Ge-P	NF/S, Chopper, 25/25/25V, 2A, 0,3W	2a	Spe,Ssi	—
2N6720	Si-N	S/Vid, 175V, 1A, 2W, >30MHz	30e	Nsc	2SC2665, 2SC2946, (BF466..466, ++)
2N6721	Si-N	=2N6721: 225V	30e		2SC2885, 2SC2946, (BF467..466, ++)
2N6722	Si-N	=2N6721: 275V	30e		2SC2665, 2SC2946, (BF466, BF666, ++)
2N6723	Si-N	=2N6721: 325V	30e		2SC2665, 2SC2946, (BF468, BF668, ++)
2N6724	Si-N-Darl	NF-Tr/E, 50V, 2A, 1W, B>15000	7e	Gen,Nsc	2SD1222, 2SD1759, (BD411..412)
2N6725	Si-N-Darl	=2N6724: 60V	7a		2SD1222, 2SD1759
2N6726	Si-P	NF-Tr/E, 40V, 2A, 1,2W, >50MHz	30e	Gen,Nsc	2SB938..839, (BD518, BD526, ++)
2N6727	Si-P	=2N6726: 50V	30e		2SB836..839, (BD518, BD526, ++)
2N6728	Si-P	Uni, 60V, 2A, 1,2W, >50MHz	30e	Gen,Nsc	2SB957..958, (BD518, BD526, ++)
2N6729	Si-P	=2N6728: 80V	30e		2SB957..958, (BD520, BD526, ++)

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2N673	Ge-P	=2N672: 1W	2a	Spe,Ssi	—
2N6730	Si-P	=2N6728: 100V	30e		2SB957..958, (BD530)
2N6731	Si-N	Uni, 100V, 1A, 2W, >50MHz	30e	Nsc	2SD1281..84, (BD529)
2N6732	Si-P	Uni, 100V, 1A, 2W, >50MHz	30e	Nsc	2SB957..960, (BD530)
2N6733	Si-N	Vid, 160V, 0,1A, 1,2W, >50MHz	30e	Gen,Nsc	2SC2870, 2SC2924, 2SC3408, (BF617,++)
2N6734	Si-N	=2N6733: 250V	30e		2SC2870, 2SC2924, 2SC3408, (BF617,++)
2N6735	Si-N	=2N6733: 300V	30e		2SC2870, 2SC2924, 2SC3406, (BF617,++)
2N6737	Si-N	S, 60V, >300MHz, <-/60ns	30e	Nsc	—
2N6738	Si-N	S-L, 450/300V, 8A, 100W, >15MHz	17j	Fer,Rca	BUT54, BUT56(A), 2SC3039, 2SC4108, ++
2N6739	Si-N	=2N6738: 550/350V	17j		BUT54, BUT56(A), 2SC3039, 2SC4108, ++
2N674	Ge-P	NF/S, Chopper, 75/75/70V, 2A, 0,3W	2a	Spe,Ssi	—
2N6740	Si-N	=2N6738: 650/400V	17j		BUT54, BUT56(A), MJE13006..07, ++
2N675	Ge-P	=2N674: 1W	2a	Spe,Ssi	—
2N6751	Si-N	S-L, 800/400V, 10A, 150W, >15MHz	23a	Fer,Rca	BUS12(A), BUW35..38, BUX80..81, ++
2N6752	Si-N	=2N6751: 650/450V	23a		BUS12(A), BUW36, BUX81, MJ8504, ++
2N6753	Si-N	=2N6751: 900/500V	23a		BUS12A, BUW38, BUX81, MJ8504, ++
2N6754	Si-N	=2N6751: 1000/500V	23a		BUS12A, BUX81, MJ8504, 2SC3215, ++
2N6755	MOS-N-FET-e	=2N6756: 60V, 8A, <0,25Ω(8A)	23a		2SK398..399, 2SK500, 2SK633
2N6756	MOS-N-FET-e	V-MOS, S-L, 100V, 14A, 75W, <0,18Ω(9A)	23a	USA,Inr,Mot	BUZ38, BUZ350, 2SK822
2N6757	MOS-N-FET-e	=2N6758: 150V, 8A, <0,6Ω(5A)	23a		2SK399, 2SK401, 2SK631, 2SK633
2N6758	MOS-N-FET-e	V-MOS, S-L, 200V, 9A, 75W, <0,4Ω(6A)	23a	USA,Inr,Mot	2SK412, 2SK633
2N6759	MOS-N-FET-e	V-MOS, S-L, 350V, 4,5A, 75W, <1,5Ω(3A)	23a	USA,Inr,Mot	BUZ63, 2SK259..260
2N676	Ge/Si-P-Darl	60V, 7A, B>1000		Adv	—
2N6760	MOS-N-FET-e	V-MOS, S-L, 400V, 5,5A, 75W, <1Ω(3,5A)	23a	USA,Inr,Mot	BUZ63, 2SK260, 2SK298
2N6761	MOS-N-FET-e	=2N6762: 450V, 4A, <2Ω(2,5A)	23a		BUZ84, 2SK351
2N6762	MOS-N-FET-e	V-MOS, S-L, 500V, 4,5A, 75W, <1,5Ω(3A)	23a	USA,Inr,Mot	BUZ84, 2SK351
2N6763	MOS-N-FET-e	=2N6764: 60V, 31A, <0,08Ω(20A)	23a		BUZ24, BUZ349, 2SK561, 2SK906
2N6764	MOS-N-FET-e	V-MOS, S-L, 100V, 38A, 150W, <0,055Ω	23a	USA,Inr,Mot	BUZ345, 2SK850
2N6765	MOS-N-FET-e	=2N6766: 150V, 18A, <0,12Ω(16A)	23a		BUZ38, BUZ350, 2SK622
2N6766	MOS-N-FET-e	V-MOS, S-L, 200V, 30A, 150W, <0,085Ω	23a	USA,Inr,Mot	—
2N6767	MOS-N-FET-e	=2N6768: 350V, 12A, <0,4Ω(7,75A)	23a		BUZ64, BUZ325, 2SK312, 2SK351
2N6766	MOS-N-FET-e	V-MOS, S-L, 400V, 14A, 150W, <0,3Ω(9A)	23a	USA,Inr,Mot	BUZ323, BUZ338, 2SK788, 2SK899
2N6769	MOS-N-FET-e	=2N6770: 450V, 11A, <0,5Ω(7A)	23a		BUZ45, BUZ339, BUZ384, 2SK512, ++
2N677	Ge-P	NF/S-L, 50V, 15A, 90W	23a	USA	AUY29, 2N1550..52, 2N1554..56, 2N1559..60
2N6770	MOS-N-FET-e	V-MOS, S-L, 500V, 12A, 150W, <0,4Ω(7A)	23a	USA,Inr,Mot	BUZ45, BUZ339, BUZ384, 2SK512, ++
2N6771	Si-N	S-L, 450/300V, 1A, 40W, >10MHz	17j	Fer,Rca	BUW40(A,B), BUX84..85, TIP49..50, ++
2N6772	Si-N	=2N6771: 550/350V	17j		BUW40A,B, BUX84..85, 2SC3352, ++
2N6773	Si-N	=2N6771: 650/400V	17j		BUW40B, BUX84..85, 2SC3352, ++
2N6774	Si-N+Di	S-L, 450/800V, 15A, 175W, >15MHz	23a	Rca	—
2N6775	Si-N+Di	=2N6774: 550/350V	23a		—
2N6776	Si-N+Di	=2N6774: 650/400V	23a		—
2N677A	Ge-P	=2N677: 60V	23a		2N1550..52, 2N1554..F1604356, 2N1559..60
2N677B	Ge-P	=2N677: 90V	23a		2N1552, 2N1556, 2N1560
2N677C	Ge-P	=2N677: 100V	23a		2N1552, 2N1556, 2N1560
2N678	Ge-P	NF/S-L, 50V, 15A, 90W	23a	USA	AUY29, 2N1550..52, 2N1554..56, 2N1559..60
2N6782	MOS-N-FET-e	V-MOS, S, 100V, 3,5A, 15W, <0,6Ω(2A)	2a	Inr,Mot	(2SK429..430)
2N6784	MOS-N-FET-e	V-MOS, S, 200V, 2,25A, 15W, <1,5Ω(1,5A)	2a	Inr,Mot	BST95
2N6766	MOS-N-FET-e	V-MOS, S, 400V, 1,25A, 15W, <3,6Ω(0,8A)	2a	Inr	(2SK535, 2SK579..580)
2N6766	MOS-N-FET-e	V-MOS, NF/S, 100V, 6A, 20W, <0,3Ω(3,5A)	2a	Inr,Mot,Six	—
2N678A	Ge-P	=2N678: 60V	23a		2N1550..52, 2N1554..56, 2N1559..60
2N678B	Ge-P	=2N678: 90V	23a		2N1552, 2N1556, 2N1560
2N678C	Ge-P	=2N678: 100V	23a		2N1552, 2N1556, 2N1560
2N679	Ge-N	NF/S, 25V, 0,15W, 3MHz	2a	USA	AC127, ASY28..29
2N6790	MOS-N-FET-e	V-MOS, S, 200V, 3,5A, 20W, <0,8Ω(2,2A)	2a	Inr,Six	—
2N6792	MOS-N-FET-e	V-MOS, S, 400V, 2A, 20W, <1,8Ω(1,25A)	2a	Inr,Six	—
2N6794	MOS-N-FET-e	V-MOS, S, 500V, 1,5A, 20W, <3Ω(3A)	2a	Inr,Six	—
2N6796	MOS-N-FET-e	V-MOS, S, 100V, 8A, 25W, <0,16Ω(5A)	2a	Inr,Six	—
2N6796	MOS-N-FET-e	V-MOS, S, 200V, 5,5A, 25W, <0,4Ω(3,5A)	2a	Inr,Six	—
2N68(/13)	Ge-P	NF-L, 30V, 1,5A	≈37	USA	—
2N680	Ge-P	NF, 30V, 0,5A, 0,15W, 3MHz	3a	USA	AC125..128, AC151, 2SB54, 2SB56
2N6800	MOS-N-FET-e	V-MOS, 400V, 3A, 25W, <1Ω(2A), <65/90ns	2a	Inr,Six	—
2N6802	MOS-N-FET-e	V-MOS, S, 500V, 3,5A, 25W, <1,5Ω(1,5A)	2a	Inr,Six	—
2N6804	MOS-N-FET-e	V-MOS, 100V, 11A, 75W, <0,3Ω(6,5A)	23a	Inr	2SJ112..113
2N6806	MOS-N-FET-e	V-MOS, 200V, 6,5A, 75W, <0,8Ω(4A)	23a	Inr	2SJ56, 2SJ114
2N681(A)	50Hz-Thy	25V, 16A(Tc=65°), Igt/Ih<40/<50mA	21b	USA,EUR	T12N100, MCR70-1, C228U, 2N3896, ++
2N681(A)S	F-Thy	=2N681: <12μs	21b		T12F100, C234U, MCR1718-5

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2N682(A)	50Hz-Thy	=2N681: 50V	21b		T12N100, MCR70-2, C228F, 2N3896, ++
2N882(A)S	F-Thy	=2N682: <12µs	21b		T12F100, C234F, MCR1718-5
2N6823+A16070	MOS-N-FET-e	V-MOS, 800V, 3A, 100W, <2,8Ω(3A)	23a	Mot	BUZ307, BUZ360..361, 28K415, 2SK954
2N6826	MOS-N-FET-e	V-MOS, 800V, 6A, 150W, <1,8Ω(6A)	23a	Mot	BUZ94, BUZ332A, 2SK684, 2SK1032
2N683(A)	50Hz-Thy	=2N681: 100V	21b		T12N100, MCR70-3, C226A, 2N3896, ++
2N683(A)S	F-Thy	=2N683: <12µs	21b		T12F100, C234A, MCR1718-5
2N6833	Si-N	S-L, SMPS, 850/450V, 5A, 60W, >15MHz	17j	Mot	BUT11(A), BUT46(A), BUV46(A), 2SC3047, ++
2N6834	Si-N	=2N6833: 125W	23a		BU426(A), BU526(A), BUS11(A), BUW11(A)++
2N6835	Si-N	S-L, SMPS, 850/450V, 6A, 150W, >10MHz	23a	Mot	BU426(A), BU526(A), BUS12(A), BUW12(A)++
2N6836	Si-N	S-L, SMPS, 850/450V, 15A, 175W, >10MHz	23a	Mot	BUS13(A), BUW46, BUX48(A..C), ++
2N6837	Si-N	S-L, SMPS, 850/450V, 20A, 250W, >10MHz	23a	Mot	BUS14(A), BUS96(A), BUX348(A), ++
2N684(A)	50Hz-Thy	=2N681: 150V	21b		T12N200, C228B, 2N3897, MCR3635-4, ++
2N884(A)S	F-Thy	=2N684: <12µs	21b		T12F200, C234B, MCR1718-5
2N6845	MOS-P-FET-e	V-MOS, 100V, 4A, 20W, <0,8Ω(2,25A)	2a	Mot	—
2N6847	MOS-P-FET-e	V-MOS, 200V, 2,5A, 20W, <1,5Ω(2,25A)	2a	Mot	—
2N6849	MOS-P-FET-e	V-MOS, 100V, 8,5A, 25W, <0,3Ω(4,1A)	2a	Mot, Six	—
2N685(A)	50Hz-Thy	=2N681: 200V	21h		T12N200, C228B, 2N3697, MCR3935-4, ++
2N685(A)S	F-Thy	=2N685: <12µs	21b		T12F200, C234B, MCR1718-5
2N6851	MOS-P-FET-e	V-MOS, 200V, 4A, 25W, <0,8Ω(2,4A)	2a	Mot, Six	—
2N686(A)	50Hz-Thy	=2N681: 250V	21b		T12N300, C228C, 2N3898, MCR3935-5, ++
2N686(A)S	F-Thy	=2N668: <12µs	21b		T12F300, C234C, MCR1718-5
2N687(A)	50Hz-Thy	=2N681: 300V	21b		T12N300, C228C, 2N3898, MCR3935-5, ++
2N687(A)S	F-Thy	=2N687: <12µs	21b		T12F300, C234C, MCR1718-5
2N686(A)	50Hz-Thy	=2N681: 400V	21b		T12N400, C228D, 2N3898, MCR3935-6, ++
2N686(A)S	F-Thy	=2N668: <12µs	21b		T12F400, C234D, MCR1718-6
2N689(A)	50Hz-Thy	=2N681: 500V	21b		T12N500, C228E, 2N3899, MCR3935-7, ++
2N689(A)S	F-Thy	=2N689: <12µs	21b		T12F500, C234E, MCR1718-7
2N6895	MOS-P-FET-e	V-MOS, 100V, 1,18A, 8,33W, <3,85Ω	2a	Inr	—
2N6896	MOS-P-FET-e	V-MOS, 100V, 6A, 60W, <0,8Ω(3,8A)	23a	Inr	2SJ55..56, 2SJ115, 2SJ118..119
2N6897	MOS-P-FET-e	V-MOS, 100V, 12A, 100W, <0,3Ω(7,6A)	23a	Inr	2SJ112..113, 2SJ127, 2SJ131
2N6896	MOS-P-FET-e	V-MOS, 100V, 25A, 150W, <0,2Ω(15,6A)	23a	Inr	—

2N69 .... 2N69

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2N690(A)	50Hz-Thy	=2N681: 600V	21b		T12N600, C228M, 2N3899, MCR3935-8, ++
2N690(A)S	F-Thy	=2N690: <12µs	21b		T12F600, C234M, MCR1718-8
2N6901	MOS-N-FET-e	V-MOS, LogL, 100V, 1,69A, <1,4Ω(1A)	2a	Inr	—
2N8902	MOS-N-FET-e	V-MOS, LogL, 100V, 12A, 75W, <0,2Ω	23a	Inr	2N6785
2N6903	MOS-N-FET-e	V-MOS, LogL, 200V, 0,98A, 8,33W, <3,65Ω	2a	Inr	—
2N6904	MOS-N-FET-e	V-MOS, Logl, 200V, 6A, 75W, <0,8Ω	23a	Inr	—
2N6905	N-FET	Dual, 55V, Idss=0,5..10mA, ΔUgs<5mV	TO-71	Six	—
2N6906	N-FET	=2N6905: ΔUgs<10mV	TO-71		—
2N6907	N-FET	=2N6905: ΔUgs<25mV	TO-71		—
2N8908	N-FET	30V, Up<-1,8V	5	Six	—
2N6909	N-FET	30V, Up<-2,3V	5	Six	—
2N691(A)	50Hz-Thy	=2N681: 700V	21b		T12N700, MCR3935-9, BStE4146N, ++
2N691(A)S	F-Thy	=2N691: <12µs	21b		T12F700, TAG35S-700
2N8910	N-FET	30V, Up<-3,5V	5	Six	—
2N692(A)	50Hz+B16115-Thy	=2N681: 600V	21b		T12N600, MCR3635-10, BStE4153N, ++
2N892(A)S	F-Thy	=2N692: <12µs	21b		T12F800, TAG35S-800
2N8928	Si-N	S-L, 450/300V, 8A, 100W, <500/2900ns	17j	Tho	MJE13006..07, BUT12(A), BUT56(A), ++
2N6929	Si-N	=2N6928: 550/350V	17j		MJE13006..07, BUT12(A), BUT56(A), ++
2N8930	Si-N	=2N6928: 650/400V	17j		MJE13006..07, BUT12(A), BUT56(A), ++
2N8931	Si-N	S-Reg, 450/300V, 10A, 150W, <0,8/3µs	18j	Tho	BUV47(A), BUW12(A), BUW13(A), 28C4157, +
2N6932	Si-N	=2N3932: 850/400V	18j		BUV47(A), BUW12(A), BUW13(A), 2SC4157, +
2N6933	Si-N	S-Reg, 450/300V, 15A, 175W, <0,8/3µs	18j	Tho	BUP23(A..C), BUV46(A), BUW13(A), ++
2N6934	Si-N	=2N6933: 550/350V	18j		BUP23(A..C), BUV46(A), BUW13(A), ++
2N8935	Si-N	=2N6933: 650/400V	18j		BUP23(A..C), BUV48(A), BUW13(A), ++
2N694	Ge-P	VHF, 30V, 0,05A, 0,1W, 500MHz	5g	Wes	AF139, AF239(S)
2N695	Ge-P	S/VHF, 15V, 0,05A, 0,075W, 250MHz	5g	Sty	AF106, AF109R, AF306
2N696(A,S)	Si-N	NF/S, 60V, 1A, 0,6..0,8W, >40MHz	2a	USA, EUR	BC140..141, BC300..302, 2N3053, ++
2N8962	MOS-N-FET-e	V-MOS, 100V, 30A, on=0,8Ω	49	Six	—
2N6963	MOS-N-FET-e	V-MOS, 200V, 30A, on=0,09Ω	49	Six	—
2N8964	MOS-N-FET-e	V-MOS, 400V, 15A, on=0,3Ω	49	Six	—
2N6985	MOS-N-FET-e	V-MOS, 500V, 13A, on=0,4Ω	49	Six	—
2N897(A,S)	Si-N	NF/S, 60V, 1A, 0,6..0,8W, >50MHz	2a	USA, EUR	BC140..141, BC300..302, 2N3053, ++
2N6975	MOS-N-FET-e	V-MOS, 400V, 5A, 100W, <100/1400ns	23a	Inr	—

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2N6976	MOS-N-FET-e	=2N6975: 500V	23a		—
2N6977	MOS-N-FET-e	=2N6975: <100/900ns	23a		—
2N6978	MOS-N-FET-e	=2N6975: 500V, <100/900ns	23a		—
2N698	Si-N	NF/S, 120V, 1A, 0,8W, 70MHz	2a	USA,Mot,Sgs	BSS42..43, BSW67..68, BSX47, 2N2405++
2N6985	Si-N	UHF, Push-Pull, 60V, 16A, PQ=125W(400MHz)		Mot	—
2N6968	Si-N	UHF, Push-Pull, 60V, 16A, PQ=100W(500MHz)		Mot	—
2N699(A,B)	Si-N	NF/S, 120V, 1A, 0,6..0,78W, 100MHz	2a	USA,Mot,Sgs	BSS42..43, BSW67..68, BSX47, 2N2405++
2N700(A,/18)	Ge-P	AM/FM, 25V, 0,05A, 0,075W, 800MHz	5g	USA, Mot	AF106, AF109R, AF139, AF239(S)
2N7000	MOS-N-FET-e	V-MOS, 60V, 0,2A, 0,4W, <5Ω, <10/10ns	7e	Mot,Nsc,Phi	BS170, BST70, BST72
2N7000	MOS-N-FET-e			Six	—
2N7001	MOS-N-FET-e	SMD, V-MOS, 240V, 50mA, <45Ω, <30/-ns	35	Six	—
2N7002	MOS-N-FET-e	SMD, V-MOS, 60V, ±0,115A, <7,5Ω(0,5A)	35a	Mot,Nsc,Phi	—
2N7002	MOS-N-FET-e			Six	—
2N7004	MOS-N-FET	V-MOS, 100V, 1A, on=0,6Ω	4-DIP	Six	—
2N7005	MOS-N-FET	V-MOS, 200V, 0,6A, on=1,5Ω	4-DIP	Six	—
2N7006	MOS-N-FET	V-MOS, 350V, 0,32A, on=5Ω	4-DIP	Six	—
2N7007	MOS-N-FET	240V, 70mA, 0,4W, on<45Ω, <30/-ns	7	Six	—
2N7008	MOS-N-FET	60V, 0,15A, 0,4W, on<7,5Ω, <20/-ns	7	Six	—
2N701	Ge-P	VHF, 30V, 0,075W, 200MHz	5g	Mot	AF106, AF109R, AF306
2N7010	MOS-N-FET	V-MOS, 60V, 1,3A, on=0,35Ω	30	Six	—
2N7012	MOS-N-FET	V-MOS, 60V, 1,2A, 1W, <0,35Ω, <50/55ns	4-DIP	Six	—
2N7013	MOS-N-FET	V-MOS, 40V, 1,2A, on=0,3Ω	4-DIP	Six	—
2N7016	MOS-N-FET	V-MOS, 60V, 0,6A, on=1Ω	4-DIP	Six	—
2N702	Si-N	Uni, 25V, 0,05A, 0,3W, 150MHz, B>20	2a	USA, Mot	BC168, BC183, BC238, BC548, ++
2N703	Si-N	=2N702: B>40	2a	USA, Mot	BC168, BC183, BC238, BC548, ++
2N705(A)	Ge-P	S, 15V, 0,05..0,1A, 0,15W, 55/135ns	2a	USA, Mot	ASZ21, 2N964A, 2N2635, 2N2955..57
2N7051	Si-N-Darl	100V, B>20k, >100MHz	7e	Nsc	—
2N7052	Si-N-Darl	100V, 1,5A, 0,625W, B=1..20k, >200MHz	7e	Nsc	2SD1660, 2SD1978, 2SD1981, 2SD2067, ++
2N7053	Si-N-Darl	100V, 1,5A, 0,825W, B=1..20k, >200MHz	7e	Nsc	2SD1660, 2SD1978, 2SD1981, 2SD2067, ++
2N7056	MOS-FET	V-MOS, 200V, 19A, 70W, on<0,1Ω(16A)	18	Sgs	—
2N7059	MOS-FET	V-MOS, 500V, 8A, 70W, on<0,45Ω(7A)	18	Sgs	—
2N706(A..C)	Si-N	S, 25..40V, 0,2A, 0,3W, 30/50ns	2a	USA,EUR	BSS11..12, BSX19..20, 2N2368..69(A), ++
2N707	Si-N	VHF-O, 56V, 0,1A, 0,3W, 350MHz	2a	USA,Mot,Sgs	BFX94..95
2N7071	MOS-N-FET-e	V-MOS, 100V, 23A, 100W, <0,1Ω(15A)	18f	Six	BUK426-100, (2SK622, 2SK629)
2N7072	MOS-N-FET-e	V-MOS, 200V, 16A, 100W, <0,2Ω(10A)	18f	Six	(BUZ350)
2N7073	MOS-N-FET-e	V-MOS, 400V, 9A, 100W, <0,55Ω(5,5A)	18f	Six	2SK1225, 2SK1328, (BUZ330..331, BUZ501)
2N7074	MOS-N-FET-e	V-MOS, 500V, 7A, 100W, <0,85Ω(4,5A)	18f	Six	2SK1206, (BUZ330..331, BUZ332A)
2N7075	MOS-N-FET-e	V-MOS, 100V, 30A, 150W, <65mΩ(24A)	18f	Six	(BUZ349, 2SK906)
2N7076	MOS-N-FET-e	V-MOS, 200V, 26A, 150W, <0,1Ω(16A)	18f	Six	(BUZ341, 2SK851)
2N7077	MOS-N-FET-e	V-MOS, 400V, 15A, 150W, <0,3Ω(9,5A)	18f	Six	2SK1268..F161791269, (BUZ323, 2SK788, 2SK899)
2N7078	MOS-N-FET-e	V-MOS, 500V, 13A, 150W, <0,4Ω(6A)	18f	Six	2SK1269, (BUZ338, 2SK725, 2SK768, 2SK899)
2N7079	MOS-N-FET-e	V-MOS, 100V, 17A, 100W, <0,21Ω(6A)	18f	Six	2SJ222
2N707A	Si-N	=2N707: 70V	2a		—
2N708	Si-N	S, 40V, 0,2A, 0,38W, <40/70ns	2a	USA,EUR	BSS10..11, BSX19..20, 2N2368..69(A), ++
2N7080	MOS-N-FET-e	V-MOS, 200V, 9,5A, 100W, <0,5Ω(6,1A)	18f	Six	(2SJ114)
2N7081	MOS-N-FET-e	V-MOS, 100V, 12A, 45W, <0,15Ω(7,7A)	17c	Six	BUK545-100, 2SK1230, 2SK1306
2N7082	MOS-N-FET-e	V-MOS, 200V, 9A, 50W, <0,3Ω(5,5A)	17c	Six	BUK545-200, (BUZ30, BUZ73)
2N7085	MOS-N-FET-e	V-MOS, 100V, 20A, 60W, <75mΩ(12A)	17c	Six	2SK1307, 2SK1318, (BUZ21..22)
2N7068	MOS-N-FET-e	V-MOS, 100V, 14A, 60W, <0,16Ω(8,5A)	17c	Six	(BUZ30A)
2N7089	MOS-N-FET-e	V-MOS, 100V, 10A, 60W, <0,3Ω(6,7A)	17c	Six	BUK545-100, 2SK1230, 2SK1305, (BUZ72)
2N708A	Si-N	=2N708: 50V	2e		BSS10..11, BSX19..20, 2N2368..68(A), ++
2N709(A)	Si-N	SS, 15V, 0,3..0,36W, <15/15ns	2a	U9A,EUR	BSS11..12, BSY17..18, 2N2368..69(A), ++
2N7090	MOS-N-FET-e	V-MOS, 200V, 5,7A, 60W, <0,8Ω(3,8A)	17c	Six	BUK444-200, BUZ73(A)F, (2SK924)
2N7091	MOS-N-FET-e	V-MOS, 100V, 14A, 70W, <0,2Ω(8,7A)	17c	Six	BUK445-100, 2SK1308, (2SK919, 2SK922)
2N7092	MOS-N-FET-e	V-MOS, 200V, 6A, 70W, <0,5Ω(5,1A)	17c	Six	BUK545-200, (BUZ30, BUZ73)
2N71	Ge-P	NF/S, 75V, 0,25A, 1W		Whs	—
2N710(A)	Ge-P	S, 15V, 0,05A, 0,15W, <75/125ns	2e	USA	ASZ21, 2N705(A), 2N2635, 2N2955..57
2N7104	MOS-N-FET-e	30V, on<70Ω, <2/-ns	5	Six	—
2N7105	MOS-N-FET-e	30V, on<70Ω, <2/-ns	5	Six	—
2N7106	MOS-N-FET-e	10V, on<70Ω, <2/-ns	5	Six	—
2N7107	MOS-N-FET-e	10V, on<70Ω, <2/-ns	5	Six	—
2N7108	MOS-N-FET-e	20V, on<70Ω, <2/-ns	5	Six	—
2N7109	MOS-N-FET-e	20V, on<70Ω, <2/-ns	5	Six	—
2N711(A,B)	Ge-P	S, 12..18V, 0,05A, 0,15W, <100/150ns	2a	USA,Mot,Tix	ASZ21, 2N705(A), 2N2635, 2N2955..57
2N7116	MOS-N-FET-e	20V, on<70Ω, <2/-ns	16-DIP	Six	—
2N7117	MOS-N-FET-e	10V, on<70Ω, <2/-ns	16-DIP	Six	—

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2N7118	MOS-N-FET-e	15V, on<70Ω, <2/-ns	16-DIP	Six	—
2N715	Si-N	HF-Tr, 50V, 0,1A, 0,5W, >70MHz	2a	USA	BFX94..95
2N716	Si-N	=2N715: 70V	2a	USA	—
2N717	Si-N	Uni, 60V, 0,5A, 0,4W, 300MHz, B>20	2a	USA,EUR	BC337A, BC637, BC639, BCX24, ++
2N717A	Si-N	=2N717: 75V	2a		BC639, BCX24, 2SD667, 2SD1226, ++
2N718	Si-N	=2N717: B>40	2a	USA,EUR	BC337A, BC637, BC639, BCX24, ++
2N718A	Si-N	=2N717: 75V, B>40	2a		BC639, BCX24, 2SD667, 2SD1226, ++
2N719(A)	Si-N	Uni, 120V, 1A, 0,4W, >40MHz, B>20	2a	USA,Sgs,Tix	BCX22, 2N3700..01, 2SD667, 2SD774
2N72	Ge-P	HF, 40V, 8mA, 0,05W		Rca	AF124..127, AF200
2N720(A)	Si-N	=2N719: >50MHz, B>40	2a	USA,Sgs,Tix	BCX22, 2N3700..01, 2SD667, 2SD774
2N721(A)	Si-N	Uni, 50V, 0,5A, 0,4W, >50MHz, B>20	2a	USA,EUR	BC337, BC637, BC639, BCX24, ++
2N722(A)	Si-N	=2N721 >60MHz, B>30	2a	USA,EUR	BC337, BC637, BC639, BCX24, ++
2N7224	MOS-N-FET-e	V-MOS, 100V, 34A, 150W, <0,081Ω(24A)	18f	Six	(2SK1149, 2SK1435..1436)
2N7225	MOS-N-FET-e	V-MOS, 200V, 27,4A, 150W, <0,105Ω(27A)	18f	Six	(2SK1670)
2N7227	MOS-N-FET-e	V-MOS, 400V, 14A, 150W, <0,415Ω(14A)	18f	Six	(2SK1268..F162681269, 2SK1453)
2N7228	MOS-N-FET-e	V-MOS, 500V, 12A, 150W, <0,515Ω(12A)	18f	Six	(2SK1269, 2SK1331, 2SK1524)
2N725	Ge-P	S, 15V, 0,05A, 0,15W, <70/100ns	2a	Sty	ASZ21, 2N705(A), 2N2635, 2N2955..57
2N726	Si-P	Uni, 25V, 0,05A, 0,3W, >140MHz, B>15	2a	USA,Mot,Tix	BC213, BC258, BC308, BC558, ++
2N727	Si-P	=2N726: B>30	2a	USA,Mot,Tix	BC213, BC258, BC308, BC558, ++
2N728	Si-N	SS, 15V, 0,1A, 0,3W, 18/-ns	2a	Sem,Sty	BSS11..12, BSY17..18, 2N2368..69(A), ++
2N729	Si-N	=2N728: 30V	2a	Sem,Sty	BSS11..12, BSX19..20, 2N2368..69(A), ++
2N73	Ge-P	S, -/50V, 0,2W		Whs	(ASY48, ASY77)
2N730	Si-N	Uni, 60V, 1A, 0,5W, >25MHz, B>20	2a	USA,Mot,Tix	BC337A, BC637, BC639, BCX24, ++
2N731	Si-N	=2N730: B>40	2a	USA,Mot,Tix	BC337A, BC637, BC639, BCX24, ++
2N734(A)	Si-N	NF/S, 60V, 0,05A, 0,5W, 150MHz, β>20	2a	USA,Mot,Tix	BC546, 2SC1890(A), 2SC2240, 2SC2459, ++
2N735(A)	Si-N	=2N734: 180MHz, β>40	2a	USA,Mot,Tix	BC546, 2SC1890(A), 2SC2240, 2SC2459, ++
2N736(A, B)	Si-N	=2N734: 180MHz, β>60	2a	USA,Mot,Tix	BC546, 2SC1890(A), 2SC2240, 2SC2459, ++
2N738(A)	Si-N	NF/S, 125V, 0,05A, 0,5W, 150MHz, β>20	2a	USA,Mot,Tix	2SC1890A, 2SC2240, 2SC2459, 2SC3245, ++
2N739(A)	Si-N	=2N738: 180MHz, β>30	2a	USA,Mot,Tix	2SC1890A, 2SC2240, 2SC2459, 2SC3245, ++
2N74	Ge-P	S, -/50V, 0,2W		Whs	(ASY48, ASY77)
2N740(A)	Si-N	=2N738: 180MHz, β>60	2a	USA,Mot,Tix	2SC1890A, 2SC2240, 2SC2459, 2SC3245, ++
2N741(A)	Ge-P	VHF-O, 15..20V, 0,1A, 360MHz	2a	USA, Mot	(AF139, AF239(S), AFY18)
2N742(A)	Si-N	NF/S, 60V, 0,1A, 0,5W, >60MHz	2a	USA	BC174, BC162, BC190, BC546, ++
2N743	Si-N	SS, 20V, 0,2A, 0,3W, <16/24ns	2a	USA,EUR	BSS11..12, BSY17..18, 2N2368..69(A), ++
2N743A	Si-N	=2N743: 40V, <12/30ns	2a		BSS11..12, BSX19..20, 2N2368..69(A), ++
2N744	Si-N	SS, 20V, 0,2A, 0,3W, <16/24ns	2a	USA,EUR	BSS11..12, BSY17..18, 2N2368..69(A), ++
2N744A	Si-N	=2N744: 40V, <12/30ns	2a		BSS11..12, BSY19..20, 2N2368..69(A), ++
2N745	Si-N	Uni, 45V, 0,02A, 0,15W, 30MHz	37b	Ray	BC167, BC182, BC237, BC547, ++
2N746	Si-N	Uni, 45V, 0,02A, 0,15W, 45MHz	37b	Ray	BC167, BC182, BC237, BC547, ++
2N747	Si-N	Uni, 25V, 0,05A, 0,2W, 60MHz	37b	Ray	BC168, BC163, BC236, BC546, ++
2N748	Si-N	Uni, 30V, 0,05A, 0,2W, 50MHz	37b	Ray	BC168, BC163, BC238, BC546, ++
2N749	Si-N	Uni, 45V, 0,05A, 0,2W, 75MHz	37b	Ray	BC167, BC182, BC237, BC547, ++
2N75	Ge-P	S, -/20V, 0,2W		Whs	(ASY26, ASY48, ASY76..77)
2N750	Si-N	Uni, 50V, 0,05A, 0,2W, 40MHz	37b	Ray	BC167, BC162, BC237, BC547, ++
2N751	Si-N	Uni, 20V, 0,05A, 0,2W, 30MHz	37b	Ray	BC168, BC162, BC236, BC546, ++
2N752	Si-N	Uni, 85V, 0,1A, 0,5W, >200MHz	2a	USA	BC546, 2SC2240, 2SC2459, 2SC3245, ++
2N753	Si-N	S, 25V, 0,05A, 0,3W, 30/60ns	2a	USA,EUR	BSS11..12, BSY17..18, 2N2368..69(A), ++
2N754	Si-N	Uni, 60V, 0,05A, 0,3A, >30MHz	2a	USA	BC174, BC162, BC190, BC546, ++
2N755	Si-N	=2N754: 100V	2a	USA	2SC1890(A), 2SC2240, 2SC2459, 2SC3245, ++
2N756	Si-N	Uni, 45V, 0,1A, 0,5W, >50MHz, β>12	2a	USA	BC167, BC162, BC237, BC547, ++
2N756A	Si-N	=2N756: 60V	2a		BC174, BC162, BC190, BC546, ++
2N757	Si-N	Uni, 45V, 0,1A, 0,5W, >50MHz, β>18	2a	USA	BC167, BC182, BC237, BC547, ++
2N757A	Si-N	=2N757: 60V	2a		BC174, BC162, BC190, BC546, ++
2N758	Si-N	Uni, 45V, 0,1A, 0,5W, >50MHz, β>18	2a	USA	BC167, BC162, BC237, BC547, ++
2N758A, B	Si-N	=2N758: 60V	2a		BC174, BC162, BC190, BC546, ++
2N759	Si-N	Uni, 45V, 0,1A, 0,5W, >50MHz, β>36	2a	USA	BC167, BC162, BC237, BC547, ++
2N759A, B	Si-N	=2N759: 60V	2a		BC174, BC162, BC190, BC546, ++
2N76	Ge-P	NF/S, 20V, 0,01A, 0,05W	1a	Gen	AC125..126, AC151, ASY26..27
2N760	Si-N	Uni, 45V, 0,1A, 0,5W, >50MHz, β>76	2a	USA,Tix	BC167, BC162, BC237, BC547, ++
2N760A, B	Si-N	=2N760: 60V	2a		BC174, BC162, BC190, BC546, ++
2N761	Si-N	Uni, 50V, 0,1A, 0,5W, >50MHz, β>19	2a	USA	BC167, BC162, BC237, BC547, ++
2N762	Si-N	=2N761: β>39	2a	USA	BC167, BC162, BC237, BC547, ++
2N764	GTO-Thy	30V, 0,2A, Igt/Ih<1/<5mA	2a	Sem,Sld	—
2N765	GTO-Thy	=2N764: 60V	2a	Sem,Sld	—
2N766	GTO-Thy	=2N764: 100V	2a	Sem,Sld	—
2N767	GTO-Thy	=2N764: 200V	2a	Sem,Sld	—

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2N768	Ge-P	S, 12V, 0,1A, 0,035W, >125MHz	2a	USA	ASZ21, 2N960..967, 2N2635, 2N2955..57
2N769	Ge-P	S, 12V, 0,1A, 0,035W, >100MHz	2a	USA	ASZ21, 2N960. F16324967, 2N2635, 2N2955..57
2N77	Ge-P	HF/S, 25V, 0,015A, 0,035W	37a	Csr,Etc	(AC 125..126, AC 151, ASY 26..27)
2N770	Si-N	HF, 20V, 0,1A, 0,15W, 125MHz	2a	Phc	BC 238, BC 548, BSW41, 2N706A ++
2N771	Si-N	HF, 20V, 0,1A, 0,15W, 200MHz	2a	Phc	BC 238, BC 548, BSW41, 2N706A, ++
2N772	Si-N	HF, 20V, 0,1A, 0,15W, 110MHz	2a	Phc	BC 238, BC 548, BSW41, 2N706A, ++
2N773	Si-N	HF, 20V, 0,1A, 0,15W, 70MHz	2a	Phc	BC 238, BC 548, BSW41, 2N706A, ++
2N774	Si-N	HF, 20V, 0,1A, 0,15W, 90MHz	2a	Phc	BC 238, BC 548, BSW41, 2N706A, ++
2N775	Si-N	HF, 20V, 0,1A, 0,15W, 160MHz	2a	Phc	BC 238, BC 548, BSW41, 2N706A, ++
2N776	Si-N	HF, 20V, 0,1A, 0,15W, 120MHz	2a	Phc	BC238, BC 548, BSW41, 2N706A, ++
2N777	Si-N	HF, 20V, 0,1A, 0,15W, 160MHz	2a	Phc	BC 238, BC 548, BSW41, 2N706A, ++
2N778	Si-N	HF, 20V, 0,1A, 0,15W, 160MHz	2a	Phc	BC 238, BC 548, BSW41, 2N706A, ++
2N779(A, B)	Ge-P	S, 15V, 0,1A, 0,06..0,15W, >320MHz	2a	USA	ASZ21, 2N964A, 2N2635, 2N2955..57
2N78	Ge-N	HF, 20V, 0,02A, 0,065W	2a	Csr,Etc	(ASY 26..29)
2N760	Si-N	Uni, 45V, 0,05A, 0,3W, >60MHz	2a	USA,Tix	BC 187, BC 182, BC 237, BC 547, ++
2N781	Ge-P	S, 15V, 0,2A, 0,15W, <60/70ns	2a	USA	2N705, 2N960..967
2N782	Ge-P	S, 12V, 0,2A, 0, 15W, <75/75ns	2a	USA	2N705, 2N960..967
2N783	Si-N	SS, 40V, 0,2A, 0,3W, <18/30ns	2a	USA,Fch,Itt	BSS 10..11, BSX 19..20, 2N2368..69(A), ++
2N784	Si-N	SS, 30V, 0,2A, 0,3W, <20/40ns	2a	USA,Fch,Itt	BSS 10..11, BSX 19..20, 2N2368..69(A), ++
2N784A	Si-N	=2N784: 40V	2a		BSS 10..11, BSX 19..20, 2N2368..69(A), ++
2N785	Ge-P	12V, 0,05W			—
2N769	Si-N	Uni, 45V, 0,025A, 0,15W, >1MHz	37b	Ray	BC 167, BC 182, BC237, BC 547, ++
2N78A	Ge-N	=2N78: 20V	2a		(ASY 26..29)
2N79	Ge-P	NF/S, 30V, 0,05A, 0,035W	1a	Rca	AC 125..126, AC 151, ASY26
2N790	Si-N	Uni, 45V, 0,025A, 0,15W, >2MHz	37b	Ray	BC 167, BC 182, BC237, BC 547, ++
2N791	Si-N	Uni, 45V, 0,025A, 0,15W, >8MHz	37b	Ray	BC 187, BC 182, BC237, BC 547, ++
2N792	Si-N	Uni, 45V, 0,025A, 0,15W, >2MHz	37b	Ray	BC 167, BC 182, BC237, BC 547, ++
2N793	Si-N	Uni, 45V, 0,025A, 0,15W, >2MHz	37b	Ray	BC 167, BC 182, BC237, BC 547, ++
2N794	Ge-P	S, 13V, 0,1A, 0,12W, 300/-ns	2a	USA	ASZ21, 2N705, 2N960..967
2N795	Ge-P	S, 13V, 0,1A, 0,12W, 150/-ns	2a	USA	ASZ21, 2N705, 2N960..967
2N796	Ge-P	S, 12V, 0,1A, 0,12W, 130/-ne	2a	USA	ASZ21, 2N705, 2N960..967
2N797	Ge-N	VHF/S, 20V, 0,15A, 0,15W, 1000MHz	2a	USA,Tix	—
2N799	Ge-P	NF/S, 25V, 0,1A, 0,075W, >4MHz	37b	Ray	ASY 26..27, ASY76..77
2N80	Ge-P	NF/S, 25V, 8mA, 0,05W	≈2a	Cbs	AC125..126, AC 151, ASY 26..27
2N800	Ge-P	=2N799:		Ray	—
2N601	Ge-P	NF/S, 30V, 0,4A, 0,075W, >3MHz	37b	Ray	ASY 76..77
2N802	Ge-P	=2N601:		Ray	—
2N803	Ge-P	NF/S, 30V, 0,4A, 0,075W, >5MHz	37b	Ray	ASY 76..77
2N804	Ge-P	=2N803:		Ray	—
2N805	Ge-P	NF/S, 30V, 0,4A, 0,075W, >10MHz	37b	Ray	ASY 76..77
2N806	Ge-P	=2N605:		Ray	—
2N607	Ge-P	NF/S, 25V, 0,1A, 0,075W, 18MHz	37b	Ray	ASY 26..27, ASY 76..77
2N808	Ge-P	=2N807:		Ray	—
2N809	Ge-P	NF/S, 30V, 0,2A, 0,075W, >3MHz	37b	Ray	ASY 26..27, ASY78..77
2N81	Ge-P	NF/S, 20V, 15mA, 0,05W	1a	Gen	AC 125..126, AC 151, ASY26..27
2N810	Ge-P	=2N809:		Ray	—
2N811	Ge-P	NF/S, 30V, 0,2A, 0,075W, >5MHz	37b	Ray	ASY 26..27, ASY76..77
2N812	Ge-P	=2N811:		Ray	—
2N813	Ge-P	NF/S, 30V, 0,2A, 0,075W, >15MHz	37b	Ray	ASY 26..27, ASY 76..77
2N814	Ge-P	=2N813:		Ray	—
2N815	Ge-N	NF/S, 25V, 0,2A, 0,075W, 8MHz	37b	Ray	ASY 26..29, ASY73..75
2N816	Ge-N	=2N815:		Ray	—
2N817	Ge-N	NF/S, 30V, 0,4A, 0,075W, >2,5MHz	37b	Ray	ASY 73..75
2N818	Ge-N	=2N817+C16261:		Ray	—
2N819	Ge-N	NF/S, 30V, 0,4A, 0,075W, >5MHz	37b	Ray	ASY 73..75
2N82	Ge-P	NF/S, 20V, 15mA, 0,035W	≈2a	Cbs	AC125..126, AC 151, ASY 26..27
2N820	Ge-N	=2N819:		Ray	—
2N821	Ge-N	NF/S, 30V, 0,4A, 0,075W, >10MHz	37b	Ray	ASY 73..75
2N822	Ge-N	=2N821:		Ray	—
2N823	Ge-N	NF/S, 25V, 0,1A, 0,075W, >4MHz	37b	Ray	ASY 28..29, ASY 73..75
2N824	Ge-N	=2N823:		Ray	—
2N825	Ge-P	NF/S, 30V, 0,4A, 0,07W, 8MHz	37b	Ray,Sty	ASY 76..77
2N826	Ge-P	=2N825:		Ray,Sty	—
2N827	Ge-P	S, 20V, 0,1A, 0,15W, 25/30ns	2a	USA, Mot	2N960..967
2N828(A)	Ge-P	S, 15V, 0,1A, 0,15W, <70/100ns	2a	USA, Mot	2N960..967
2N829	Ge-P	S, 15V, 0,1A, 0,15W, 35/60ns	2a	USA, Mot	2N960..967

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2N83(A)	Ge-P	S/Tr-L, 66V, 2..3A, 10W	≈37	Tra	—
2N834	Si-N	S, 40V, 0,2A, 0,3W, <33/75ns	2a	USA,EUR	BSS 10..11, BSX 19..20, 2N2368..69(A),++
2N834A	Si-N	=2N834: <16/24ns	2a		BSS 10..11, BSX 19..20, 2N2368..69(A),++
2N835	Si-N	S, 25V, 0,2A, 0,3W, <20/35ns	2a	USA,EUR	BSS 10..11, BSX 19..20, 2N2368..69(A),++
2N837	Ge-P	S, 12V, 0,1A, 0,15W, <30/90ns	2a	USA	ASZ21, 2N705, 2N960..967
2N838	Ge-P	SS, 30V, 0,1A, 0,15W, 17/20ns	2a	USA, Mot	2N960..967
2N838	Si-N	Uni, 45V, 0,05A, 0,3W, >30MHz, B>15	2a	USA	BC 167, BC 182, BC237, BC 547, ++
2N84(A)	Ge-P	S/Tr-L, 50V, 2..3A, 10W	≈37	Tra	—
2N840	Si-N	=2N839: B>30	2a	USA, Mot	BC 167, BC 182, BC237, BC 547, ++
2N841	Si-N	=2N839: >40MHz, B>60	2a	USA, Mot	BC 167, BC 182, BC237, BC 547, ++
2N842	Si-N	NF/S, 45V, 0,05A, 0,3W, >30MHz, B>20	2a	USA	BC 167, BC 182, BC237, BC 547, ++
2N843	Si-N	=2N842: >40MHz, B>45	2a	USA, Mot	BC 167, BC 182, BC237, BC 547, ++
2N844	Si-N	NF/S, 60V, 0,05A, 0,3W, >50MHz	2a	USA	BC 174, BC 182, BC 190, BC 546, ++
2N845	Si-N	=2N844: 100V	2a	USA	2SC1890A, 2SC2240, 2SC2459, 2SD755, ++
2N846	Ge-P	S, 15V, 0,05A, 0,06W, >320MHz	2a	Phc,Spr	ASZ21, 2N705, 2N960..967
2N846A,B	Ge-P	=2N848: 0,1A, 0,15W	2a		ASZ21, 2N705, 2N960..967
2N847	Si-N	S, 40V, 0,05A, 0,2W, <32/58ns	2a	Ray	BSS 10..11, BSV91..92, 2N2368..69(A),++
2N848	Si-N	=2N847: 20V	2a	Ray	BSS 10..11, BSV91..92, 2N2368..89(A),++
2N849	Si-N	S, 25V, 0,05A, 0,3W, <40/25ns	24c	Sca, Tix	BSS 11..12, BSV91..92, 2N2388..69(A),++
2N85	Ge-P	NF-Tr, 20V, 0,1A, 0,2W	2a	Tra	(AC125..126, AC 151, 2SB56)
2N850	Si-N	S, 25V, 0,05A, 0,3W, <40/35ns	24c	Sca, Tix	BSS 11..12, BSV91..92, 2N2368..69(A),++
2N851	Si-N	S, 20V, 0,2A, 0,3W, <16/24ns	24c	Sca, Tix	BSS 11..12, BSX 19..20, 2N2368..69(A),++
2N852	Si-N	S, 20V, 0,2A, 0,3W, <16/24ns	24c	Sca, Tix	BSS 11..12, BSX 19..20, 2N2368..69(A),++
2N853	Si-P	NF/S, 40V, 0,05A, 0,15W, >5MHz	2a	USA	(BC212, BC257, BC307, BC557,++)
2N859	Si-P	NF/S, 40V, 0,05A, 0,15W, >6MHz	2a	USA	(BC212, BC257, BC307, BC557,++)
2N86	Ge-P	NF-Tr, 45V, 0,1A, 0,2W	2a	Tra	(2SB56A)
2N860	Si-P	NF/S, 25V, 0,05A, 0,15W, >6,5MHz	2a	USA, Mot	(BC213, BC258, BC308, BC558,++)
2N861	Si-P	NF/S, 25V, 0,05A, 0,15W, >7,5MHz	2a	USA	(BC213, BC258, BC308, BC558,++)
2N862	Si-P	NF/S, 15V, 0,05A, 0,15W, >6MHz	2a	USA	(BC213, BC258, BC308, BC558,++)
2N863	Si-P	NF/S, 15V, 0,05A, 0,15W, >10MHz	2a	USA	(BC213, BC258, BC308, BC558,++)
2N864	Si-P	NF/S, 6V, 0,05A, 0,15W, >16MHz	2a	USA	(BC213, BC258, BC308, BC558,++)
2N864A	Si-P	=2N864: 0,1A	2a	Tdy	(BC213, BC258, BC308, BC558,++)
2N865	Si-P	NF/S, 10V, 0,05A, 0,15W, >24MHz	2a	USA	(BC213, BC258, BC308, BC558,++)
2N965A	Si-P	=2N865: 0,1A	2a	Tdy	(BC213, BC258, BC308, BC558,++)
2N866	Si-N	NF-Tr, 30V, 0,6A, 0,5W, >40MHz	2a	Sty	BC337..338, BC 635, BC 637, BC 639, ++
2N867	Si-N	NF-Tr, 30V, 0,6A, 0,5W, >50MHz	2a	Sty	BC337..338, BC 635, BC 637, BC 639, ++
2N869	Si-P	HF/S, 25V, 0,2A, 0,36W, 300MHz	2a	USA,Mot,Sgs	BSW24, 2N3905..06, 2N4125..26
2N969A	Si-P	=2N869: >400MHz	2a		BSW24, 2N3905..F1638206, 2N4125..26
2N87	Ge-P	NF-Tr, 25V, 0,1A, 0,2W	≈1a	Tra	(AC 125..128, AC 151, 2SB56)
2N870	Si-N	NF/S, 100V, 0,5W, >50MHz	2a	USA,Sgs,Tix	BC639, BCX24, 2N3700..01, 2SD667, ++
2N871	Si-N	=2N870: >60MHz	2a	USA	BC639, BCX24, 2N3700..01, 2SD667, ++
2N876	50Hz-Thy	15V, 0,32A(Tc=70°), Igt/Ih<0,2/<5mA	2a	USA,Tho,Tix	TAG06Y, (2N2322, 2N6332, TAG615-100,++)-
2N877	50Hz-Thy	=2N878: 30V	2a		TAG06Y, (2N2323, 2N6332, TAG615-100,++)
2N878	50Hz-Thy	=2N876: 60V	2a		TAG06YY, (2N2324, 2N6334, TAG615-100,++)
2N879	50Hz-Thy	=2N878: 100V	2a		TAG06A, (2N2324, 2N6334, TAG615-100,++)
2N89	Ge-P	0,025W	37d	Tra	—
2N860	50Hz-Thy	=2N876: 150V	2a		TAG06B, (2N2325, 2N6335, TAG615-200,++)
2N861	50Hz-Thy	=2N876: 200V	2a		TAG06B, (2N2326, 2N6335, TAG615-200,++)
2N882	50Hz-Thy	=2N876: 300V	2a		TAG06C, (2N2328, 2N6336, TAG615-300,++)
2N863	50Hz-Thy	=2N876: 400V	2a		TAG06D, (2N2329, 2N6337, TAG615-400,++)
2N864	50Hz-Thy	15V, 0,32A(Tc=70°), Igt/Ih<0,02/<3mA	2a	USA, Tho, Tix	(2N2322A)
2N865	50Hz-Thy	=2N884: 30V	2a		(2N2323A)
2N866	50Hz-Thy	=2N884: 60V	2a		(2N2324A)
2N867	50Hz-Thy	=2N884: 100V	2a		(2N2324A)
2N866	50Hz-Thy	=2N884: 150V	2a		(2N2325A)
2N869	50Hz-Thy	=2N884: 200V	2a		(2N2326A)
2N89	Ge-P	0,025W	37d	Tra	—
2N890	50Hz-Thy	=2N884: 300V	2a		(2N2328A)
2N891	50Hz-Thy	=2N884: 400V	2a		(2N2329A)
2N692	GTO-Thy	15V, 0,25A(Tc=70°), Igt/Ih<0,05/<1mA	2a	USA, Fch	—
2N893	GTO-Thy	=2N892	2a		—
2N894	GTO-Thy	=2N892: 30V	2a		—
2N895	GTO-Thy	=2N892: 30V	2a		—
2N896	GTO-Thy	=2N892: 60V	2a		—
2N697	GTO-Thy	=2N892: 60V	2a		—
2N898	GTO-Thy	=2N892: 100V	2a		—

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2N899	GTO-Thy	=2N892: 100V	2a		—
2N90	Ge-P	0,025W	37d	Tra	—
2N900	GTO-Thy	=2N892: 200V	2a		—
2N901	GTO-Thy	=2N892: 200V	2a		—
2N902	Si-N	NF/S, 45V, 0,025A, 0,15W, >1MHz		Ray	(BC167, BC182, BC237, BC547, ++)
2N903	Si-N	NF/S, 45V, 0,025A, 0,15W, >2MHz		Ray	TBC167, BC182, BC237, BC547, ++)
2N904	Si-N	NF/S, 45V, 0,025A, 0,15W, >8MHz		Ray	(BC167, BC182, BC237, BC547, ++)
2N905	Si-N	NF/S, 45V, 0,025A, 0,15W, >2MHz		Ray	(BC167, BC182, BC237, BC547, ++)
2N906	Si-N	NF/S, 45V, 0,025A, 0,15W, >2MHz		Ray	(BC167, BC182, BC237, BC547, ++)
2N907	Si-N	NF/S, 45V, 0,025A, 0,15W, >12MHz		Ray	(BC167, BC182, BC237, BC547, ++)
2N906	Si-N	NF/S, 45V, 0,025A, 0,15W, >25MHz		Ray	(BC167, BC182, BC237, BC547, ++)
2N909	Si-N	Uni, 60V, 1A, 0,5W, >50MHz	2a	USA, Fch	BC337A, BC637, BC639, BCX24, ++
2N91	Ge-P	NF/S, 15V, 0,5A, 0,125W	2a	Tra	AC128, AC152..153, AC188, 2SB405
2N910	Si-N	NF/S, 100V, 1A, 0,5W, >60MHz	2a	USA, Mot, Sgs	BC639, BCX24, 2N3700..01, 2SD667, ++
2N911	Si-N	NF/S, 100V, 1A, 0,5W, >50MHz	2a	USA, Mot, Sgs	BC639, BCX24, 2N3700..01, 2SD667, ++
2N912	Si-N	NF/S, 100V, 1A, 0,5W, >40MHz	2a	USA, Mot, Sgs	BC639, BCX24, 2N3700..01, 2SD667, ++
2N913	Si-N	VHF, 25V, 0,86W, 650MHz	2a	Idi, Sca	BF224..225, BF614, BF502..508, ++
2N914(A)	Si-N	S, 40V, 0,5A, 0,66W, <40/40ns	2a	USA, EUR	BSS10, BSX26, BSX89, 2N8261
2N915	Si-N	HF/S, 70V, 0,86W, >250MHz	2a	USA, EUR	BSW68..64, 2N2221..22(A)
2N915A	Si-N	=2N915: >500MHz	2a		(BSW68..64, 2N2221..22(A))
2N916(A)	Si-N	VHF/S, 45V, 0,05A, 0,88W, >800MHz	2a	USA, EUR	BF224..225, BSW88..64, 2N2221..22(A)++
2N916B	Si-N	=2N916: 60V, >500MHz	2a		(BF224..225, BSW88..64, 2N2221..22(A)++)
2N917(A)	Si-N	VHF/UHF, 60V, 0,05A, 0,2W, 900MHz	5g	USA, EUR	BF877..676, BF689, BF788, 2N2857, ++
2N918	Si-N	VHF/UHF, 60V, 0,05A, 0,2W, >600MHz	5g	USA, EUR	BF677..876, BF689, BF788, 2N2857, ++
2N919	Si-N	Uni, 25V, 0,22A, 0,86W, >200MHz, B>20	2a	Csr, Elc	BC168, BC188, BC266, BC548, ++
2N92	Ge-P	NF/S, 25V, 0,2A, 0,125W	2a	Tra	AC125..126, AC151, ASY26..27
2N920	Si-N	=2N919: B>40	2a	Csr, Elc, Sgs	BC168, BC188, BC288, BC548, ++
2N921	Si-N	Uni, 50V, 0,2A, 0,36W, 400MHz, B>20	2a	Csr, Elc	BC167, BC162, BC237, BC547, ++
2N922	Si-N	=2N921: B>40	2a	Csr, Elc	BC167, BC182, BC237, BC547, ++
2N923	Si-P	Uni, 40V, 0,05A, 0,15W, β>12	2a	USA	BC212, BC257, BC307, BC557, ++
2N924	Si-P	Uni, 40V, 0,05A, 0,15W, β>24	2a	USA	BC212, BC257, BC307, BC557, ++
2N925	Si-P	Uni, 50V, 0,05A, 0,15W, β>10	2a	USA	BC212, BC257, BC307, BC557, ++
2N928	Si-P	Uni, 50V, 0,05A, 0,15W, β>20	2a	USA	BC212, BC257, BC307, BC557, ++
2N927	Si-P	Uni, 70V, 0,05A, 0,15W, β>6	2a	USA	BC212, BC256, BC266, BC556, ++
2N928	Si-P	Uni, 70V, 0,05A, 0,15W, β>16	2a	USA	BC212, BC256, BC266, BC556, ++
2N929	Si-N	Uni, ra, 45V, 0,03A, 0,5W, >30MHz	2a	USA, EUR	BC414, BC550, 2N2483..84, 2N3117, ++
2N929A	Si-N	=2N929: 60V	2a		BC414, BC550, 2N2483..84, 2N3117, ++

2 N 93 .... 2 N 93

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2N930	Si-N	Uni, ra, 45V, 0,03A, 0,5W, >30MHz	2a	USA, EUR	BC414, BC550, 2N2483..84, 2N3117, ++
2N930A,B	Si-N	=2N929: 60V	2a		BC414, BC550, 2N2483..64, 2N3117, ++
2N934	Ge-P	S, 13V, 0,2A, 0,15W, >35MHz	2a	Ray, Sty	2N705, 2N960..887
2N935	Si-P	Uni, 50V, 0,05A, 0,25W, β>9	2a	USA	(BC212, BC257, BC307, BC557, ++)
2N936	Si-P	Uni, 50V, 0,05A, 0,25W, β>16	2a	USA	(BC212, BC257, BC307, BC557, ++)
2N937	Si-P	Uni, 50V, 0,05A, 0,25W, β>36	2a	USA	(BC212, BC257, BC307, BC557, ++)
2N936	Si-P	Uni, 40V, 0,1A, 0,25W, β>9	2a	USA	(BC212, BC257, BC307, BC557, ++)
2N939	Si-P	Uni, 40V, 0,1A, 0,25W, β>18	2a	USA	(BC212, BC257, BC307, BC557, ++)
2N94(A)	Ge-N	HF, 20V, 0,3A, 0,15W	2a	Csr, Etc	ASY28..29, ASY73..75
2N940	Si-P	Uni, 40V, 0,1A, 0,25W, β>36	2a	USA	(BC212, BC257, BC307, BC557, ++)
2N941	Si-P	S, Chopper, 25/8/25V, 0,05A, 0,25W	2a	USA	—
2N942	Si-P	S, Chopper, 25/8/25V, 0,05A, 0,25W	2a	USA	—
2N943	Si-P	S, Chopper, 40/18/40V, 0,05A, 0,25W	2a	USA	—
2N944	Si-P	S, Chopper, 40/18/40V, 0,05A, 0,25W	2a	USA	—
2N945	Si-P	S, Chopper, 50/50/50V, 0,05A, 0,25W	2a	USA	—
2N946	Si-P	S, Chopper, 50/50/50V, 0,05A, 0,25W	2a	USA	—
2N947	Si-N	S, 20V, 0,1A, 0,26W, >200MHz	2a	USA	BC238, BC546, BSY62..63, 2N706A, ++
2N946	50Hz-Thy	30V, 0,26A(Tc=125°), Igt/Ih<0,02/<1mA	2a	USA, Fch	(2N2322A)
2N949	50Hz-Thy	=2N948: 60V	2a		(2N2324A)
2N95(/13)	Ge-N	NF, 30V, 1,5A, 2,5W	~37	USA	—
2N950	50Hz-Thy	=2N946: 100V	2a		(2N2324A)
2N951	50Hz-Thy	=2N946: 200V	2a		(2N2326A)
2N955	Ge-N	UHF, S, 12V, 0,1A, 0,15W, 1GHz	2a	Sem	—
2N955A	Ge-N	=2N955: 0,5A	2a		—
2N956	Si-N	NF-Tr, 75V, 0,5W, 300MHz	2a	USA, EUR	BC639, BCX24, 2N3700..01, 2SD667, ++
2N957	Si-N	Uni, 40V, 0,25W, >200MHz	2a	USA, Fch	BC167, BC182, BC237, BC547, ++
2N956	Si-N	Uni, 25V, 0,2A, 0,25W, >200MHz, B>20	24c	Trw	(BC166, BC163, BC238, BC546, ++)

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2N959	Si-N	=2N958: B>40	24c	Trw	(BC168, BC183, BC238, BC548,++)
2N96	Ge-P	NF, 30V, 0,2A, 0,05W	2a	Rca	AC125..126, AC151, ASY26
2N960	Ge-P	S, 15V, 0,1A, 0,15W, <50/85ns	2a	USA,Mot,Tix	ASZ21, 2N705
2N961	Ge-P	S, 15V, 0,1A, 0,15W, <50/85ns	2a	USA,Mot,Tix	ASZ21, 2N705(A)
2N962	Ge-P	S, 12V, 0,1A, 0,15W, <50/100ns	2a	USA,Mot,Tix	ASZ21, 2N705(A)
2N963	Ge-P	S, 12V, 0,1A, 0,15W, <50/120ns	2a	USA,Mot,Tix	ASZ21, 2N705(A)
2N964(A)	Ge-P	S, 15V, 0,1A, 0,15W, <50/85ns	2a	USA,Mot,Tix	ASZ21, 2N705(A)
2N965	Ge-P	S, 12V, 0,1A, 0,15W, <50/85ns	2a	USA,Mot,Tix	ASZ21, 2N705(A)
2N966	Ge-P	S, 12V, 0,1A, 0,15W, 50/85ns	2a	USA,Mot,Tix	ASZ21, 2N705(A)
2N967	Ge-P	S, 12V, 0,1A, 0,15W, <60/120ns	2a	USA,Mot,Tix	ASZ21, 2N705(A)
2N966	Ge-P	S, 15V, 0,2A, 0,15W, 50/70ns	2a	USA, Mot	2N705, 2N960..987
2N969	Ge-P	S, 12V, 0,2A, 0,15W, 50/70ns	2a	USA, Mot	2N705, 2N960..987
2N97(A)	Ge-N	NF/HF, 20V, 0,02A, 0,05W	2a	USA	(AC127, 2SD39)
2N970	Ge-P	S, 12V, 0,2A, 0,15W, 65/100ns	2a	USA, Mot	2N705, 2N960..967
2N971	Ge-P	S, 7V, 0,2A, 0,15W, 65/100ns	2a	USA, Mot	2N705, 2N960..987
2N972	Ge-P	S, 15V, 0,2A, 0,15W, 50/75ns	2a	USA, Mot	2N705, 2N960..967
2N973	Ge-P	S, 12V, 0,2A, 0,15W, 50/75ns	2a	USA, Mot	2N705, 2N960..967
2N974	Ge-P	S, 12V, 0,2A, 0,15W, 85/100ns	2a	USA, Mot	2N705, 2N960..987
2N975	Ge-P	S, 7V, 0,2A, 0,15W, 65/100ns	2a	USA, Mot	2N705, 2N960..967
2N976	Ge-P	S, 15V, 0,1A, 0,1W, >250MHz	2a	USA	2N705, 2N960..967
2N977	Ge-P	S, 15V, 0,2A, 0,15W, >400MHz	2a	USA	2N705, 2N960..967
2N978	Si-P	Uni, 30V, 0,6A, 0,33W, >40MHz	2a	USA,Mot,Sgs	BC327..328, BC636, BC636, BC640,++
2N979	Ge-P	S, 20/15V, 0,1A, 0,06W, >100MHz	2a	USA	ASZ21, 2N705, 2N960..967
2N96(A)	Ge-N	NF/HF, 20V, 0,03A, 0,05W	2a	USA	(AC127, 2SD39)
2N980	Ge-P	=2N979: 20/12V	2a	USA	ASZ21, 2N705, 2N960..967
2N981	Si-N	Uni, 80V, 0,1A, 0,5W, >50MHz	2a	USA,Nsc	BC546, 2SC1890(A), 2SC2240, 2SC2459,++
2N982	Ge-P	S, 20V, 0,1A, 0,06W, 450MHz	2a	USA	ASZ21, 2N705, 2N960..967
2N983	Ge-P	=2N982: 15V	2a	USA	ASZ21, 2N705, 2N960..967
2N984	Ge-P	=2N982: 15V	2a	USA	ASZ21, 2N705, 2N960..967
2N985	Ge-P	S, 15V, 0,2A, 0,15W, <35/80ns	2a	USA, Mot	2N705, 2N960..987
2N966	Opto				—
2N967	Ge-P	HF, 40V, 10mA, 0,1W, >40MHz	5g	USA	AF124..128, AF200
2N966	Si-N	Uni, 20V, 0,22A, 0,3W, >300MHz	2a	USA	BC168, BC183, BC238, BC548,++
2N989	Si-N	Uni, 20V, 0,22A, 0,3W, >300MHz	2a	USA	BC168, BC183, BC238, BC548,++
2N99	Ge-N	NF/HF, 20V, 0,02A, 0,05W	2a	USA	(AC127, 2SD39)
2N990	Ge-P	HF, 20V, 10mA, 0,067W, >44MHz	5k	USA	AF124..128, AF200
2N991	Ge-P	HF, 20V, 10mA, 0,067W, >44MHz	5k	USA	AF124..126, AF200
2N992	Ge-P	HF, 20V, 10mA, 0,067W, >44MHz	5k	USA	AF124..128, AF200
2N993	Ge-P	HF, 20V, 10mA, 0,067W, >44MHz	5k	USA	AF124..128, AF200
2N994	Ge-P	S, 15V, 0,15A, 0,2W, <35/45ns	2a	USA	2N705, 2N960..987
2N995(A)	Si-P	Uni, 20V, 0,36W, 300MHz	2a	USA,Mot,Sgs	BC308, BC558, 2N3209, 2N4125..28,++
2N998	Si-P	Uni, 15V, 0,2A, 0,38W, >100MHz	2a	USA, Mot	BC213, BC258, BC308, BC558,++
2N997	Si-N-Darl	Uni, 75V, 0,3A, 0,5W, B>4000	5r	USA,Mot,Sgs	BFX68
2N998	Si-N-Darl	Uni, 100V, 0,5A, 0,5W, B>1600	5r	USA,Mot,Sgs	BFX68
2N999	Si-N-Darl	Uni, 60V, 0,5A, 0,5W, B>4000	5r	USA,Mot,Sgs	BFX67
2NP...2R		**2NP...2R**			
2NP	Si-N-Darl	=2SD1478-P (Typ-Code/Stempel/marking)	35		→2SD1478
2NP	Si-N-Darl	=2SD2434-P (Typ-Code/Stempel/marking)	≈35		→2SD2434
2NQ	Si-N-Darl	=2SD1478-Q (Typ-Code/Stempel/marking)	35		→2SD1478
2NQ	Si-N-Darl	=2SD2434-Q (Typ-Code/Stempel/marking)	≈35		→2SD2434
2NR	Si-N-Darl	=2SD1478-R (Typ-Code/Stempel/marking)	35		→2SD1478
2NR	Si-N-Darl	=2SD2434-R (Typ-Code/Stempel/marking)	≈35		→2SD2434
2OP	Si-N-Darl	=2SD1476A-P (Typ-Code/Stempel/marking)	38		→2SD1476A
2OQ	Si-N-Darl	=2SD1478A-Q (Typ-Code/Stempel/marking)	35		→2SD1476A
2OR	Si-N-Darl	=2SD1476A-R (Typ-Code/Stempel/marking)	35		→2SD1476A
2P	Si-N	=FMMT2222R (Typ Code/Stempel/marking)	35		→FMMT2222R
2P	Si-P	=KST5068 (Typ-Code/Stempel/marking)	35		→KST5066
2P	Si-P	=MMBT5088 (Typ-Code/Stempel/marking)	35		→MMBT5068
2P	Si-N	=SXT2222A (Typ-Code/Stempel/marking)	39		→SXT2222A
2P05M	50Hz-Thy	50V, 2A(Tc=54°), Igt/Ih<0,2/<3mA	13e	Nec	C106F1, TAG106F, C108F, TAG108F,++
2P1M	50Hz-Thy	=2P05M: 100V	13e		C106A1, TAG106A, C106A, TAG108A,++
2P2M	50Hz-Thy	=2P05M: 200V	13e		C108B1, TAG108B, C106B, TAG105B,++
2P4M	50Hz-Thy	=2P05M: 400V	13e		C106D1, TAG108D, C108D, TAG108D,++
2P5M	50Hz-Thy	=2P05M: 500V	13e		C106E1, TAG106E, C108E, TAG108E,++
2P6M	50Hz-Thy	=2P05M: 600V	13e		C106M1, TAC106M, C108M, TAG106M,++

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2PA1015(L)	Si-P	=2SA1015(L): 0,5W	7c	Phi	→2SA1015(L)
2PA733	Si-P	=2SA733: 0,5W	7c	Phi	→2SA733
2PB709(A)	Si-P	=2SB709(A)	35a	Phi	→2SB709(A)
2PC1315(L)	Si-N	=2SC1815(L): 0,5W	7c		→2SC1815(L)
2PC945	Si-N	=2SC945: 0,5W	7c	Phi	→2SC945
2PD601(A)	Si-N	→2SD601(A)	35a	Phi	→2SD601(A)
2Q	Si-P	=KST 5087 (Typ-Code/Stempel/marking)	35		→KST 5087
2Q	Si-P	=MMBT 5087 (Typ-Code/Stempel/marking)	35		→MMBT5087
2R	Si-P	=MMBT 4260 (Typ-Code/Stempel/marking)	35		→MMBT4260
2S		**2S**			
2S	Si-P	=MMBT 4261 (Typ-Code/Stempel/marking)	35		→MMBT4261
2S014[Texas]	Si-N	HF, 40V, 20mA, >10MHz	2a	Tix	BC167, BC183, BC237, BC547, ++
2S017[Texas]	Si-N	Uni, 60V, 0,4A, >2,5MHz	2e	Tix	BC140..141, BC300..302, 2N3053,++
2S018[Texas]	Si-N	Uni, 100V, 0,4A, >2,5MHz	2a	Tix	BC141, BC300, 2N1889..90, 2N1990,++
2S019[Texas]	Si-N	Uni, 60V, 0,4A, >2,5MHz	2a	Tix	BC140..141, BC300..302, 2N3053,++
2S020[Texas]	Si-N	Uni, 100V, 0,4A, >2,5MHz	2a	Tix	BC141, BC300, 2N1889..90, 2N1990,++
2S024[Texas]	Si-N	NF/HF/S-L, 100V, 75A, 100W, 12MHz		Tix	—
2S025[Texas]	Si-N	=2S024: 150V			—
2S026[Texas]	Si-N	=2S024: 200V			—
2S033(A)[Texas]	Si-N	NF/S-L, 100V, 3A, 40W, 25MHz, B>30	23a	Tix	BD245C, BDX95, 2N5758..60, 2SD895, ++
2S034[Texas]	Si-N	=2S033: B>60	23a		BD245C, BDX95, 2N5758..60, 2SD896, ++
2S035[Texas]	Si-N	=2S033: 150V	23a		BD245D, 2SD731..732, 2SC2260..62,++
2S036[Texas]	Si-N	=2S033: 150V, B>60	23a	Tix	BD245D, 2SD731..732, 2SC2260..62, ++
2S100	Ge-P	→2SB100		JAP	—
2S101	Ge-P	→2SB101		JAP	—
2S102	Ge-P	→2SB102		JAP	—
2S102[Texas]	Si-N	S, 60V, 0,05A, 0,4W, >150MHz, B>20	2a	Tix	BC162, BC190, BC546, 2N3903..04,++
2S103	Ge-P	→2SB103		JAP	—
2S103[Texas]	Si-N	=2S102: B>40	2a		BC182, BC190, BC546, 2N3903..04,++
2S104	Ge-P	→2SB104		JAP	—
2S104[Texas[	Si-N	=2S102: B>80	2a	Tix	BC162, BC190, BC546, 2N3903..04,++
2S105	Ge-P	→2SB105		JAP	—
2S108	Ge-P	→2SB108		JAP	—
2S107	Ge-P	→2SB107		JAP	—
2S108	Ge-P	→2SA108		JAP	—
2S109	Ge-P	→2SA109		JAP	—
2S11	Ge-P	→2SB68		JAP	—
2S110	Ge-P	→2SA110		JAP	—
2S111	Ga-P	→2SA111		JAP	—
2S112	Ge-P	→2SA112		JAP	—
2S113	Ge-P	→2SB12		JAP	—
2S114	Ge-P	→2SB13		JAP	—
2S115	Ge-P	→2SB14		JAP	—
2S118	Ge-P	→2SB15		JAP	—
2S119	Ge-P	→2SB16		JAP	—
2S120	Ge-P	→2SB17		JAP	—
2S121	Ge-P	→2SB18		JAP	—
2S122	Ge-P	→2SB19		JAP	—
2S123	Ge-P	→2SB20		JAP	—
2S124	Ge-P	→2SB21		JAP	—
2S125	Ge-P	→2SB22		JAP	—
2S126	Ge-P	→2SB23		JAP	—
2S131	Ge-P	→2SB131		JAP	—
2S131[Texas]	Si-N	SS, 15V, 0,2A, 0,3W, >220MHz	2a	Tix	BSS11..12, BSY17..18, 2N2368..69(A),++
2S132	Ge-P	→2SC73		JAP	—
2S133	Ge-P	→2SC75		JAP	—
2S134	Ge-P	→2SC76		JAP	—
2S135	Ge-P	→2SC77		JAP	—
2S136	Ge-P	→2SC78		JAP	—
2S136	Ge-P	→2SA124		JAP	—
2S139	Ge-P	→2SA125		JAP	—
2S140	Ge-P	→2SA80		JAP	—
2S141	Ge-P	→2SA81		JAP	—
2S142	Ge-P	→2SA82		JAP	—
2S143	Ge-P	→2SA83		JAP	—

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2S144	Ge-P	→2SA84		JAP	—
2S145	Ge-P	→2SA85		JAP	—
2S148	Ge-P	→2SB74		JAP	—
2S150	Ge-P	→2SB150		JAP	—
2S153	Ge-P	→2SA153		JAP	—
2S154	Ge-P	→2SA154		JAP	—
2S155	Ge-P	→2SA155		JAP	—
2S156	Ge-P	→2SA156		JAP	—
2S157	Ge-P	→2SA157		JAP	—
2S156	Ge-P	→2SA156		JAP	—
2S159	Ge-P	→2SA159		JAP	—
2S160	Ge-P	→2SA160		JAP	—
2S161	Ge-P	→2SB161		JAP	—
2S162	Ge-P	→2SB162		JAP	—
2S163	Ge-P	→2SB163		JAP	—
2S164	Ge-P	→2SB164		JAP	—
2S165	Ge-P	→2SB165		JAP	—
2S166	Ge-P	→2SB166		JAP	—
2S167	Ge-P	→2SA167		JAP	—
2S168	Ge-P	→2SA166		JAP	—
2S169	Ge-P	→2SA169		JAP	—
2S170	Ge-P	→2SA170		JAP	—
2S171	Ge-P	→2SA171		JAP	—
2S172	Ge-P	→2SA172		JAP	—
2S173	Ge-P	→2SA173		JAP	—
2S174	Ge-P	→2SA174		JAP	—
2S175	Ge-P	→2SA175		JAP	—
2S176	Ge-P	→2SA176		JAP	—
2S177	Ge-P	→2SB80..62		JAP	—
2S179	Ge-P	→2SB179		JAP	—
2S166	Ge-P	→2SB166		JAP	—
2S169	Ge-P	→2SB189		JAP	—
2S190	Ge-P	→2SA86		JAP	—
2S191	Ge-P	→2SA41		JAP	—
2S192	Ge-P	→2SA42		JAP	—
2S193	Ge-P	→2SB67		JAP	—
2S26(A)	Ge-P	→2SB25..26		JAP	—
2S2M	F-Thy	200V, 2A(Tc=54°), Igt/Ih<0,3/<10mA	13e	Nec	—
2S30	Ge-P	→2SA30		JAP	—
2S301	Si-P	Uni, 60V, 0,1A, 0,3W	2a	Tix	BC303, BC556, 2SA970, 2SA1265(A), ++
2S3010	Si-P	Uni, 40V, 0,15A, 0,3W	2a	Tix	BC303..304, BC307, BC557, 2N2303, ++
2S302	Si-P	=2S301: 40V	2a		BC303. 304, BC307, BC557, 2N2303, ++
2S3020	Si-P	Uni, 40V, 0,15A, 0,3W	2a	Tix	BC303..304, BC307, BC557, 2N2303, ++
2S3021	Si-P	Uni, 15V, 0,15A, 0,3W	2a	Tix	BC303..304, BC308, BC558, 2N2303, ++
2S302A	Si-P	=2S301: 25V	2a		BC303..304, BC308, BC556, 2N2303, ++
2S303	Si-P	=2S301: 25V	2a		BC303..304, BC308, BC556, 2N2303, ++
2S3030	Si-P	Uni, 25V, 0,15A, 0,3W	2a	Tix	BC303..304, BC308, BC556, 2N2303, ++
2S304	Si-P	=2S301: 15V	2a		BC303..304, BC308, BC556, 2N2303, ++
233040	Si-P	Uni, 15V, 0,15A, 0,3W	2a	Tix	BC303..304, BC308, BC556, 2N2303, ++
2S305	Si-P	=2S301: 125V	2a		BF398, 2SA970, 2SA1049, 2SA1285(A), ++
2S308	Si-P	Uni, sym, 6/6/6V, 10mA, 0,05W	2a	Tix	—
2S307	Si-P	=2S308: 15/15/15V	2a		—
2S31	Ge-P	→2SA31		JAP	—
2S32	Ge-P	→2SB32		JAP	—
2S321	Si-P	=2S301	2a	Tix	→2S301
2S322(A)	Si-P	=2S302(A)	2a		→2S302(A)
2S3220	Si-P	=2S3020	2a	Tix	→2S3020
2S3221	Si-P	=2S3021	2a		→2S3021
2S323	Si-P	=2S303	2a		→2S303
2S3230	Si-P	=2S3030	2a		→2S3030
2S324	Si-P	=2S304	2a		→2S304
2S3240	Si-P	=2S3040	2a		→2S3040
2S325	Si-P	=2S305	2a		→2S305
2S326	Si-P	=2S306	2a	Tix	—
2S327	Si-P	=2S307	2a		—
2S35	Ge-P	→2SA35		JAP	—

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2S36	Ge-P	→2SA36		JAP	—
2S39	Ge-P	→2SB39		JAP	—
2S3M	F-Thy	=2S3M: 300V	13e		—
2S41	Ge-P	→2SB41		JAP	—
2S42	Ge-P	→2SB42		JAP	—
2S43	Ge-P	→2SA43		JAP	—
2S44	Ge-P	→2SB44		JAP	—
2S45	Ge-P	→2SA45		JAP	—
2S46	Ge-P	→2SB46		JAP	—
2S47	Ge-P	→2SB47		JAP	—
2S48	Ge-P	→2SA46		JAP	—
2S49	Ge-P	→2SA49		JAP	—
2S4M	F-Thy	=2S2M: 400V	13e		—
2S50	Ge-P	→2SA50		JAP	—
2S501	Si-N	Uni, 25V, 0,03A, 0,3W, >30MHz, B>40	2a	Tix	BC168, BC183, BC236, BC548, ++
2S502	Si-N	=2S501: B>100	2a		BC168, BC183, BC236, BC548, ++
2S503	Si-N	=2S501: B>180	2a		BC168, BC183, BC236, BC548, ++
2S51	Ge-P	→2SA51		JAP	—
2S512	Si-N	S, 25V, 0,2A, 0,3W, >250MHz	2a	Tix	BSS11..12, BSX19..20, 2N2368..69(A), ++
2S52	Ge-P	→2SA52		JAP	—
2S53	Ge-P	→2SA53		JAP	—
2S54	Ge-P	→2SB54		JAP	—
2S56(A)	Ge-P	→2SB55..56, 2SB94		JAP	—
2S57	Ge-P	→2SA57		JAP	—
2S56	Ge-P	→2SA56		JAP	—
2S59	Ge-P	→2SA59		JAP	—
2S80	Ge-P	→2SA27		JAP	—
2S80A	Ge-P	→2SA60		JAP	—
2S61	Ge-P	→2SB61		JAP	—
2S64	Ge-P	→2SA64		JAP	—
2S65	Ge-P	→2SB65		JAP	—
2S721	Si-N	NF/S-L, 80V, 2A, 150W, >2MHz; B>20		Tix	(BD245A, BDV91, 2SD718, 2SD695..696++)
2S722	Si-N	=2S721: 100V			(BD245C, BDV93, 2SD718, 2SD895..896++)
2S723	Si-N	=2S721: B>40			(BD245A, BDV91, 2SD718, 2SD895..696++)
2S724	Si-N	=2S721: 100V, B>40			(BD245C, BDV93, 2SD716, 2SD895..696++)
2S74	Ge-P	→2SB173		JAP	—
2S91	Ge-P	→2SB79		JAP	—
2S92	Ge-P	→2SA28		JAP	—
2S92A	Ge-P	→2SA92		JAP	—
2S93	Ge-P	→2SA29		JAP	—
2S93A	Ge-P	→2SA93		JAP	—
2S95	Ge-P	→2SA95		JAP	—
2S95A[Texas]	Si-N	SS, 25V, 0,2A, 0,3W, >300MHz	2a	Tix	BSS11..12, BSX19..20, 2N2368..69(A), ++
2S96	Ge-P	→2SA96		JAP	—
2S97	Ge-P	→2SA97		JAP	—
2S96	Ge-P	→2SA98		JAP	—
2S99	Ge-P	→2SA99		JAP	—
2SA		**2SA**			
2SA100	Ge-P	HF/ZF, 40V, 10mA, 20MHz	2a	Mat	AF124..127, AF200, 2SA218..227
2SA1000				Mit	—
2SA1001	Si-P	NF/S-L, 130V, 8A, 80W, 40MHz	23a	Fui	2SA908, 2SA1386A), 2SB555, 2SB681, ++
2SA1002	Si-P	NF/S-L, 120V, 12A, 120W, 40MHz	23a	Fui	2SA908, 2SA1386(A), 2SB555, 2SB681, ++
2SA1003	Si-P	=2SA1002: 450V	23e		2SA908, 2SA1386(A), 2SB697, 2SB681, ++
2SA1004	Si-P	Uni, 40V, 0,1A, 0,31W, 200MHz	7e	Hit	BC213, BC257, BC307, BC557, ++
2SA1005	Si-P	FM-Tuner, HF, 40V, 0,03A, 0,25W, 400MHz	7c	Nec	BF324, BF414, BF936, BF939, BF509
2SA1006	Si-P	NF/HF-L, 180V, 1,5A, 25W, 80MHz	17j	Nec	2SA968A, B, 2SA1009(A), 2SA1133, 2SB628A
2SA1006A	Si-P	=2SA1006: 200V	17j		2SA968B, 2SA1009(A), 2SA1133
2SA1006B	Si-P	=2SA1006: 250V	17j		2SA1009(A), 2SA1236, 2SA1397
2SA1007(A)	Si-P	NF/S-L, 150V, 10A, 100W, 50MHz	23e	Nec	BDX20, 2SA1386(A), 2SB681, 2SB697, ++
2SA1006	Si-P	S-L, 100V, 2A, 15W, <0,5/2µs	17j	Nec	2SA1078..1079, 2SB719..720, 2SB861, ++
2SA1009	Si-P	S-L, 350/350V, 2A, 15W, <1/3,5µs	17j	Nec	2SA1236, 2SA1397
2SA1009A	Si-P	=2SA1009: 400/400V	17j		2SA1236, 2SA1397
2SA101	Ge-P	HF/ZF, 40V, 10mA, 15MHz	2a	Mat	AF124..127, AF200, 2SA218..227
2SA1010	Si-P	S-L, 100V, 7A, 40W, <0,5/2µs	17j	Nec	BD244C, BD544C, MJE15029, 2SA1077, ++
2SA1011	Si-P	NF/S-L, 180V, 1,5A, 25W, 100MHz	17j	Say	2SA968A, B, 2SA1112, 2SA1133, 2SB628A

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2SA1012	Si-P	S-L, lo-sat, 60V, 5A, 25W, 60MHz	17j	Tos	2SA1289..1291, 2SA1293, 2SB919
2SA1013	Si-P	CTV-NF/VA, 160V, 1A, 0,9W, >15MHz	7c(9mm)	Tos	2SA1275, 2SB1212
2SA1014	Si-P	=2SA1013: 10W	13m	Tos	(2SA913A, 2SA1112, 2SB630, 2SB861)
2SA1015	Si-P	Uni, 50V, 0,15A, 0,4W, >80MHz	7c	Tos	BC212, BC257, BC307, BC557, ++
2SA1016	Si-P	Uni, ra, 120V, 0,05A, 0,4W, 110MHz	7c	Say	2SA941, 2SA970, 2SA992, 2SA1038, ++
2SA1016K	Si-P	=2SA1016: 150V	7c		2SA1123..24
2SA1017	Si-P	NF-Tr, 120V, 0,05A, 0,5W, 110MHz	7c	Say	2SA893A, 2SA1019, 2SA1285, 2SB716(A), ++
2SA1018	Si-P	Vid, 250/200V, 0,07A, 0,75W, >50MHz	7c	Mat	BF423, BF436..437, 2SA1371..1372, ++
2SA1019	Si-P	NF-Tr, 150V, 0,05A, 0,9W, 110MHz	7c(9mm)	Say	2SA1124, 2SA1281, 2SA1285A, 2SB1348
2SA102	Ge-P	HF/ZF, 40V, 10mA, 25MHz	2a	Mat	AF124..127, AF200, 2SA218..227
2SA1020	Si-P	NF/S, 60V, 2A, 0,9W, 100MHz	7c(9mm)	Tos	2SA1382, 2SA1315, 2SB692, 2SB1312, ++
2SA1021	Si-P	TV-VA, 150V, 1,5A, 20W, >15MHz	14h	Tos	2SA1249, 2SB649
2SA1022	Si-P	SMD, ra, 30V, 0,03A, >150MHz	35a	Mat	BC859..860, BCF30, BCF70, BF550
2SA1023	Si-P	Uni, 70V, 0,1A, 0,25W, 160MHz	7c	Nec	BC556, 2SA970, 2SA1049, 2SA1285(A), ++
2SA1024	Si-P	S, 400V, 0,1A, 0,4W, 15MHz	2a	Hit	2SA1251, 2SA1372, 2SB1074
2SA1025	Si-P	Uni, 60V, 0,1A, 0,4W, 90MHz	7c	Hit	BC212, BC256, BC266, BC556, ++
2SA1026	Si-P	Uni, 50V, 0,2A, 0,25W, 100MHz	10b	Mit	BC212, BC256, BC266, BC556, ++
2SA1027	Si-P	Uni, ra, 50V, 0,2A, 0,25W, 100MHz	10b	Mit	BC214, BC416, BC560, 2SA1136..1137, ++
2SA1028	Si-P	NF/S-L, 100V, 10A, 95W, 60MHz	23a	Son	2SA1141, 2SA1146, 2SA1166
2SA1029	Si-P	Uni, 30V, 0,1A, 0,2W, 260MHz	7c	Hit	BC213, BC256, BC308, BC556, ++
2SA103	Ge-P	HF/ZF, 40V, 10mA, 35MHz	2a	Mat	AF124..127, AF200, 2SA218..227
2SA1030	Si-P	=2SA1029: 55V	7c	Hit	BC212, BC257, BC307, BC557, ++
2SA1031	Si-P	=2SA1029: ra	7c	Hit	BC214, BC259, BC309, BC559, 2SA1137+
2SA1032	Si-P	=2SA1029: 55V, ra	7c	Hit	BC214, BC416, BC560, 2SA1136..1137, ++
2SA1033	Si-P	Uni, 30V, 0,1A, 0,31W, 260MHz	7e	Hit	BC213, BC256, BC308, BC558, ++
2SA1034	Si-P	SMD, ra, 35V, 0,05A, 200MHz	35a	Mat	BC859..860, BCF29..30, BCF70
2SA1035	Si-P	=2SA1034: 55V	35a	Mat	BC860, BCF70
2SA1036(K)	Si-P	SMD, 40V, 0,5A, 200MHz	=35a, 35a	Rhm	BC807, BCW67..68, BCX17, 2SA1313, ++
2SA1037(A,K,KLN)	Si-P	SMD, ra, 50V, 0,1A, 140MHz	=35a, 35a	Rhm	BC860, BCF70
2SA1036	Si-P	Uni, ra, 120V, 0,05A, 0,3W, 140MHz	7c	Rhm	2SA941, 2SA970, 2SA992, 2SA1136, ++
2SA1039	Si-P	=2SA1036: 80V	7c	Rhm	2SA942, 2SA970, 2SA992, 2SA1136..37, ++
2SA104	Ge-P	HF/ZF, 40V, 10mA, 50MHz	2a	Mat	AF124..127, AF200, 2SA218..227
2SA1040	Si-P	S-L, 120V, 10A, 100W, 60MHz	23a	Fui	BUW96, 2SA1146, 2SA1186, 2SB552
2SA1041	Si-P	S-L, 120V, 15A, 100W, 60MHz	23a	Fui	BUW96, 2SA908..909, 2SA1147, 2SB552
2SA1042	Si-P	S-L, 70V, 15A, 100W, 60MHz	23a	Fui	BUW96, 2SA907..909, 2SA1147, 2SB552
2SA1043	Si-P	S-L, 120V, 30A, 150W, 60MHz	23a	Fui	—
2SA1044	Si-P	=2SA1043: 70V	23a	Fui	—
2SA1045	Si-P-Darl	S-L, 100V, 10A, 100W, B=3000	23a(B)	Fui	BDX64B, BDX84C, MJ4032, 2SB693, ++
2SA1046	Si-P-Darl	=2SA1045: 15A	23a(B)	Fui	BDX66B, MJ4032, 2SB693
2SA1047	Si-P	NF-Tr-L, 160V, 0,08A, 130MHz	14h	Say	BF416, BF418, BF470, BF472, 2SB1109+
2SA1046	Si-P	Uni, ra, 50V, 0,15A, 0,2W, >60MHz	41c	Tos	BC214, BC416, BC560, 2SA1136..1137, ++
2SA1049	Si-P	Uhi, 120V, 0,1A, 0,2W, 100MHz	41c	Tos	2SA970, 2SA992, 2SA1136, 2SA1285, ++
2SA105	Ge-P	RF/IF AMP, 15V, 50mA, 250MHz	2a	Ful	AF124..128, AF200, 2SA218..227
2SA1050	Si-P	NF/S-L, 140V, 12A, 100W, 70MHz	23a	Tos	2SA1227, 2SA1386, 2SB555, 2SB861, ++
2SA1050A	Si-P	=2SA1050: 120W	23a		2SA1227, 2SA1386, 2SB555, 2SB681, ++
2SA1051	Si-P	NF/S-L, 150V, 15A, 150W, 60MHz	23a	Tos	MJ15016, 2SA908..09, 2SA1117, 2SA1147++
2SA1051A	Si-P	=2SA1051: 160V	23a		MJ15016, 2SA909, 2SA1116..17, 2SA1147++
2SA1052	Si-P	SMD, 30V, 0,1A, 260MHz	35a	Hit	BC856..856, BCW29..30, BCW69..70, ++
2SA1053	Si-P	S, 40V, 0,2A, 0,8W, <70/300ns	7e	Nec	BSW24, 2N3250..51(A), 2N3905..06, ++
2SA1054	Si-P	S, 60V, 0,6A, 0,6W, <35/225ns	7e	Nec	BSW24, 2N2906..07(A), 2N4028..29
2SA1055	Si-P	S, 25V, 0,2A, 0,6W, <70/300ns	7e	Nec	B6W24, 2N3905..06, 2N4125..28, ++
2SA1058	Si-P	S, 40V, 0,6A, 0,6W, <35/225ns	7s	Nec	BSW24, 2N2906..07(A), 2N4026..29, ++
2SA1057	Si-P	UHF, 20V, 0,05A, 4GHz	52s	Nec	BFQ32, 2SA801, 2SA1223
2SA1056	Si-P	UHF, 20V, 0,05A, 2,5GHz	52s	Nec	BFQ32, BFQ78, 2SA801, 2SA1223
2SA1059	Si-P	Dual, S, 20V, 0,03A, 0,3W, <10/10ns		Nec	—
2SA106	Ge-P	RF/IF AMP, 15V, 50mA, 250MHz	2a	Ful	AF124..126, AF200, 2SA218..227
2SA1060	Si-P	NF/S-L, 60V, 5A, 60W, 15MHz	18j	Mat	BD246B, 2SB688, 2SB776, 2SB816, ++
2SA1061	Si-P	NF/S-L, 100V, 6A, 70W, 15MHz	18j	Mat	BD246C, 2SB666, 2SB776, 2SB618, ++
2SA1062	Si-P	NF/S-L, 120V, 7A, 60W, 15MHz	18j	Mat	BD246C, 2SB688, 2SB776, 2SB616, ++
2SA1063	Si-P	NF/S-L, 150V, 6A, 80W, 50MHz	23a	Mat	2SA1166, 2SB861, 2SB696 697, 2SB818, ++
2SA1064	Si-P	NF/S-L, 150V, SA, 100W, 50MHz	23a	Mat	2SA1166, 2SB861, 2SB697, 2SB817, ++
2SA1065	Si-P	NF/S-L, 150V, 10A, 120W, 50MHz	23a	Mat	2SA1166, 2SB861, 2SB697, 2SB617, ++
2SA1066	Si-P	Unl, 70V, 0,2A, 0,5W, 120MHz	7c	Soa	BC556, 2SA970, 2SA941..942, 2SA1285, ++
2SA1067	Si-P	NF/S-L, 120V, 10A, 100W, 50MHz	23a	Sak	2SA1188, 2SB861, 2SB697, 2SB817, ++
2SA1066	Si-P	=2SA1067: 150V	23a	Sak	2SA1186, 2SB861, 2SB697, 2SB817, ++
2SA1069(A)	Si-P	S-L, 60V, 5A, 30W, <0,5/3μs	17j	Nec	BD244B, BD540B, BD952, 2SA1289..90, ++

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2SA107	Ge-P	RF/IF AMP, 15V, 50mA, 250MHz	2a	Fui	AF124..127, AF200, 2SA218..227
2SA1070				Nec	—
2SA1071				Nec	—
2SA1072	Si-P	NF/S-L, 120V, 12A, 120W, 60MHz	23a	Fui	2SA1227, 2SA1386, 2SB555, 2SB681, ++
2SA1072A	Si-P	=2SA1072: 150V	23a		2SA1227A, 2SA1386, 2SB697, 2SB681, ++
2SA1073	Si-P	=2SA1072: 160V	23a	Ful	2SA1227A, 2SA1386, 2SB697, 2SB681, ++
2SA1074	Si-P	NF/S-L, 160V, 15A, 150W	23a	Ful	MJ15016, 2SA908..09, 2SA1117, 2SA1147++
2SA1075	Si-P	=2SA1072:	20j	Ful	2SA1094..1095, 2SA1166, 2SA1167, ++
2SA1076	Si-P	=2SA1073:	20j	Ful	2SA1095, 2SA1166, 2SA1215, 2SA1389, ++
2SA1077	Si-P	DC-DC-Converter, 120V, 10A, 60W, 60MHz	17j	Ful	—
2SA1078	Si-P	NF/S-L, 120V, 2A, 25W, 140MHz	17j	Ful	2SA1133, 2SB719..720
2SA1079	Si-P	=2SA1078: 160V	17j	Ful	2SA1133, 2SB719..720
2SA108	Ge-P	RF/IF AMP, 15V, 50mA, 250MHz	2a	Fui	AF124..126, AF200, 2SA218..227
2SA1080	Si-P	NF/S-L, 40V, 0,5A, 20W, 30MHz	17j	Fui	BD240, 2SA748
2SA1081	Si-P	Uni, 90V, 0,1A, 0,4W, 90MHz	7c	Hit	2SA970, 2SA1049, 2SA1166, 2SA1285(A)
2SA1082	Si-P	=2SA1081: 120V	7c	Hit	2SA970, 2SA1049, 2SA1166, 2SA1285(A)
2SA1083	Si-P	=2SA1081: ra, 60V	7c	Hit	BC416, BC560, 2SA970, 2SA1049, ++
2SA1084	Si-P	=2SA1081: ra, 90V	7c	Hit	2SA970, 2SA1049, 2SA1138
2SA1085	Si-P	=2SA1081: ra, 120V	7c	Hit	2SA970, 2SA1049, 2SA1138
2SA1086				Tcs	—
2SA1087				Tcs	—
2SA1088				Tos	—
2SA1089				Tcs	—
2SA109	Ge-P	RF/IF AMP, 15V, 50mA, 250MHz	2a	Ful	AF124..126, AF200, 2SA218..227
2SA1090	Si-P	HF/S, 60V, 0,2A, 0,3W, 250MHz	2a	Tos	BC212, BC556, 2N2906..2907(A), ++
2SA1091	Si-P	Vid, 300V, 0,1A, 0,4W, 60MHz	7c	Tos	BF437, BF421A, 2SA1371..1372, ++
2SA1092	Si-P	Uni, ra, 60V, 0,05A, 0,25W, 220MHz	7c	Mat	BC416, BC560, 2SA970, 2SA1138..1137, ++
2SA1093	Si-P	NF/HF/S-L, 120V, 8A, 60W, 90MHz	18j	Tos	2SA1141, 2SA1146, 2SA1166
2SA1094	Si-P	NF/S-L, 140V, 12A, 120W, 70MHz	20j	Tos	2SA1076, 2SA1166, 2SA1187, 2SA1389, ++
2SA1095	Si-P	=2SA1094: 160V, 15A, 150W, 60MHz	20j	Tos	2SA1076, 2SA1166(A), 2SA1215, 2SA1389, ++
2SA1096(A)	Si-P	NF/S-L, 70V, 2A, 5W, 150MHz	14h	Mat	BD378, BD380, 2SB744(A), 2SB874..75, ++
2SA1097(-1,-2)	Si-P	NF/S-L, 100..130V, 10A, 95W, 60MHz		Son	BD246C, 2SA1141, 2SA1146, 2SA1166
2SA1098				Mit	—
2SA1099				Mit	—
2SA110	Ge-P	RF/IF AMP, 15V, 50mA, 250MHz	2a	Fui	AF124..126, AF200, 2SA216..227
2SA1100	Si-P	Uni, ra, 50V, 0,2A, 0,3W, 200MHz	7b	Mit	BC214, BC416, BC560, 2SA1136..1137, ++
2SA1101				Mit	—
2SA1102	Si-P	NF/S-L, 60V, 6A, 60W, 20MHz	18j	Sak	BD246B, BDV94, 2SA1141, 2SA1227(A), ++
2SA1103	Si-P	NF/S-L, 100V, 7A, 70W, 20MHz	18j	Sak	BD246C, BDV96, 2SA1141, 2SA1227(A), ++
2SA1104	Si-P	NF/S-L, 120V, 8A, 80W, 20MHz	18j	Sak	BD246C, 2SA1141, 2SA1166, 2SA1227(A), ++
2SA1105	Si-P	NF/S-L, 120V, 9A, 90W, 20MHz	18j	Sak	BD246C, 2SA1141, 2SA1186, 2SA1227(A), ++
2SA1106	Si-P	NF/S-L, 140V, 10A, 100W, 20MHz	18j	Sak	2SA1186, 2SA1227A, 2SA1386(A), 2SB817, ++
2SA1107(A)	Si-P	NF/S-L, 150V, 10A, 120W, 50MHz	20j	Nec	2SA1076, 2SA1095, 2SA1166(A), 2SA1389, ++
2SA1108	Si-P	NF/S-L, 130V, 12A, 120W, 60MHz	20j	Nec	2SA1076, 2SA1095, 2SA1166(A), 2SA1389, ++
2SA1108A	Si-P	=2SA1108: 150V	20j		2SA1076, 2SA1095, 2SA1166(A), 2SA1389, ++
2SA1109	Si-P	NF/S-L, 160V, 10A, 200W, 60MHz	23a	Nec	MJ15016, 2SA909, 2SA1147, 2SA1116..17++
2SA111	Ge-P	RF/IF AMP, 15V, 50mA, 250MHz	2a	Fui	AF124..126, AF200, 2SA218..227
2SA1110	Si-P	NF/S-L, 120V, 0,5A, 5W, 200MHz	14h	Mat	2SA1178, 2SA1184, 2SA1220(A), 2SA1358, ++
2SA1111	Si-P	NF/S-L, 150V, 1A, 20W, 200MHz	17j	Mat	2SA913(A), 2SA968(A,B), 2SA1011, ++
2SA1112	Si-P	=2SA1111: 180V	17j		2SA913A, 2SA968A,B, 2SA1011, 2SA1133
2SA1113	Si-P	Dual, 70V, 0,2A, 0,4W, 100MHz	7-SIP	Mit	—
2SA1114	Si-P	Uni, ra, 70V, 0,2A, 0,6W, 150MHz	7b	Mit	2SA970, 2SA1049, 2SA1138..1137
2SA1115	Si-P	Uni, ra, 50V, 0,2A, 0,3W, 200MHz	41b	Mit	BC214, BC416, BC560, 2SA1138..1137, ++
2SA1116	Si-P	S-L, 200V, 15A, 150W, 20MHz	23a	Sak	MJ15016, 2SA909, 2SB552, 2SB645
2SA1117	Si-P	S-L, 200V, 17A, 200W, 20MHz	23a	Sak	—
2SA1118				Tos	—
2SA1119				Tcs	—
2SA112	Ge-P	RF/IF AMP, 15V, 50mA, 250MHz	2a	Ful	AF124..126, AF200, 2SA218..227
2SA1120	Si-P	lo-sat, 35V, 5A, 10W, 170MHz	14h	Tos	2SA1357
2SA1121	Si-P	SMD, Uni, 35V, 0,5A, 50MHz	35a	Hit	BC807, BCW67, BCX17, 2SA1326, ++
2SA1122	Si-P	SMD, Uni, 55V, 0,1A	35a	Hit	BC856..857, BCW69..70, BCW89, ++
2SA1123	Si-P	Uni, ra, 150V, 0,05A, 0,75W, 200MHz	7c	Mat	2SA1016K, 2SA1482
2SA1124	Si-P	=2SA1123: 1W	7c(9mm)	Mat	2SA1482, (2SA1016K)
2SA1125	Si-P	=2SA1123: 1,5W	17j	Mat	—
2SA1126	Si-P	S, 650V, 0,1A, 0,75W, 15MHz	2a	Hit	2SA911
2SA1127	Si-P	Uni, ra, 80V, 0,1A, 0,4W, 200MHz	7c	Mat	BC560, 2SA1049, 2SA1138..37, 2SA1335, ++

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2SA1128	Si-P	Uni, 25V, 0,5A, 0,6W, 150MHz	7c	Mat	BC327..328, BC636, 2SA1515, 2SB910, ++
2SA1129	Si-P	NF/S-L, 30V, 7A, 40W, <1/3,5µs	17j	Nec	BD244, BD544, BD796, BD806, 2SB919++
2SA113	Ge-P	RF/IF AMP, 15V, 50mA, 250MHz	2a	Fui	AF124..126, AF200, 2SA218..227
2SA1133(A)	Si-P	NF/S-L, TV-VA, 200V, 2A, 30W, 40MHz	17j	Mat	BD240F, 2SB720, 2SB861
2SA1135	Si-P	NF/S-L, 80V, 4A, 55W, 10MHz	16j	Sak	BD246B, BDV96, 2SA1141, 2SA1186, ++
2SA1136	Si-P	NF-V, ra, 120V, 0,1A, 0,3W, 90MHz	7c	Rhm	2SA941, 2SA970, 2SA992, 2SA1049, ++
2SA1137	Si-P	=2SA1136: 80V	7c		2SA941..942, 2SA970, 2SA992, 2SA1049, ++
2SA1138(1)	Si-P	Uni, ra, 80V, 0,01A, 0,6W, 190MHz	9b	Nec	2SA941..942, 2SA970, 2SA992, 2SA1049, ++
2SA1139				Nec	—
2SA114	Ge-P	RF/IF AMP, 15V, 50mA, 250MHz	2a	Fui	AF124..127, AF200, 2SA218..227
2SA1140				Nec	—
2SA1141	Si-P	NF/HF-L, 115V, 10A, 100W, 90MHz	16j	Nec	2SA1146, 2SA1186
2SA1142	Si-P	NF-Tr-L, 180V, 0,1A, 8W, 180MHz	14h	Nec	BF418, BF418, BF470, BF472, 2SA1352
2SA1143	Si-P	Uni, 20V, 0,05A, 0,2W, 100MHz	7b	Mit	BC213, BC258, BC308, BC558, ++
2SA1144	Si-P	NF-L, 150V, 0,05A, 10W, 200MHz	14h	Tos	BF416, BF418, BF470, BF472, 2SA1352
2SA1145	Si-P	=2SA1144: 0,8W	7c(9mm)	Tos	2SA1124, 2SA1281, 2SA1285A, 2SA1482, ++
2SA1146	Si-P	NF/HF/S-L, 140V, 10A, 100W, 70MHz	18j	Tos	2SA1186
2SA1147	Si-P	NF/S-L, 180V, 15A, 150W, 60MHz	23a	Tos	MJ15016, 2SA909, 2SA1116..17, 2SB645, ++
2SA1148				Tos	—
2SA1149				Tos	—
2SA115	Ge-P	RF/IF AMP, 15V, 50mA, 250MHz	2a	Fui	AF124..126, AF200, 2SA218..227
2SA1150	Si-P	Uni, 35V, 0,8A, 0,3W, 120MHz	41c	Tos	BC327..328, BC636, BC636, BC640, ++
2SA1151	Si-P	Uni, 60V, 0,1A, 0,25W, 180MHz	7c	Nec	BC212, BC256, BC266, BC556, ++
2SA1152	Si-P	HF/S, 80V, 0,3A, 0,8W, 50/450ns	7c	Nec	BC640, 2N4027, 2N4029, 2N5400..01, ++
2SA1153	Si-P	HF/S, 60V, 0,5A, 0,6W, <35/255ns	7e	Nec	BSW24, 2N2906..07(A), 2N4028..29
2SA1154	Si-P	Uni, 80V, 0,7A, 1W, 120MHz	9b	Nec	BC638, BC640, 2N2906..2907(A), ++
2SA1155	Si-P	Dual, 100V, 0,1A, 0,4W, 100MHz	7-SIP	Mit	—
2SA1156	Si-P	S-L, 400/400V, 0,5A, 10W, <1/5µs	14h	Nec	2SA1775, (2SA1400)
2SA1157				Tos	—
2SA1158	Si-P	Uni, 80V, 0,1A, 0,4W, >80MHz	7c	Tos	BC556, 2SA970, 2SA1049, 2SA1285, ++
2SA1159				Tos	—
2SA116	Ge-P	RF/IF AMP, 15V, 50mA, 250MHz	2a	Fui	AF124..125, AF200, 2SA340..342
2SA1160	Si-P	lo-sat, 20V, 2A, 0,9W, 140MHz	7c(9mm)	Tos	2SA1362, 2SB927, 2SB892, 2SB985
2SA1161	Si-P	UHF, 15V, 0,03A, 0,2W, 3,5GHz	7l	Tos	BFQ32, 2SA1057, 2SA1223, 2SA1228, ++
2SA1162	Si-P	SMD, Uni, 50V, 0,15A, >80MHz	35a	Tos	BC856..857, BCW69..70, BCW89, 2SA1311
2SA1163	Si-P	SMD, Uni, 120V, 0,1A, 100MHz	35a	Tos	2SA1312, 2SA1566
2SA1164	Si-P	HF/S, 35V, 0,1A, 0,2W, 30/320ns	7c	Tos	2N3250..51(A), 2N3905..06, 2N4034..35, ++
2SA1165				Nec	—
2SA1166	Si-P	NF/S-L, 180V, 15A, 150W, 80MHz	20j	Nec	2SA1078, 2SA1095, 2SA1215, 2SA1369, ++
2SA1166A	Si-P	=2SA1166: 180V	20j		2SA1169..1170, 2SA1216, 2SA1333, ++
2SA1167				Mit	—
2SA1168				Mit	—
2SA1169	Si-P	NF/S-L, 200V, 15A, 150W, 20MHz	20j	Sak	2SA1295, 2SA1333, 2SB756
2SA117	Ge-P	RF/IF AMP, 15V, 50mA, 250MHz	2a	Fui	AF124..125, AF200, 2SA340..342
2SA1170	Si-P	NF/S-L, 200V, 17A, 200W, 20MHz	20j	Sak	2SA1295
2SA1171	Si-P	SMD, NF/HF, 90V, 0,05A, 200MHz	35a	Hit	2SA1312, 2SA1486
2SA1173	Si-P	SMD, NF-V, 140V, 0,05A, 80MHz	39b	Nec	2SA1200, 2SB807, 2SB1046..1047
2SA1174	Si-P	Uni, ra, 120V, 0,05A, 0,3W, 100MHz	40c	Nec	2SA1016(K), 2SA1036, 2SA1123..24, ++
2SA1175	Si-P	Uni, 80V, 0,1A, 0,25W, 180MHz	40c	Nec	BC212, BC256, BC286, BC558, ++
2SA1176				Nec	—
2SA1177	Si-P	FM, 230MHz	40c	Say	BF324, BF440..441, BF450..451, ++
2SA1178	Si-P	NF/HF-L, 150V, 1A, 20W, 200MHz	14h	Mat	2SA1220A, 2SB849, 2SB1066A
2SA1179	Si-P	SMD, Uni, 55V, 0,15A, 180MHz	35a	Say	BC856..857, BCW69..70, BCW89, 2SA1312
2SA118	Ge-P	RF/IF AMP, 15V, 50mA, 250MHz	2a	Fui	AF124..125, AF200, 2SA340..342
2SA1180	Si-P	S-L, 180V, 10A, 100W	23a	Fui	MJ15018, BUW96, 2SA909, 2SA1118..17, ++
2SA1180A	Si-P	=2SA1180: 200V	23a		MJ15018, BUW86, 2SA909, 2SA1118..17, ++
2SA1181				Fui	—
2SA1182	Si-P	SMD, Uni, 35V, 0,5A, 200MHz	35a	Tos	BC807, BCW86, BCX17, 2SA1313, ++
2SA1183	Si-P	NF/S-L, 120V, 7A, 70W, B=15000	77c	Tos	BDV64C
2SA1184	Si-P	NF-Tr-L, 120V, 1A, 15W, 120MHz	14h	Tos	2SA1178, 2SA1220(A), 2SA1358, 2SB1086, ++
2SA1185	Si-P	NF/S-L, 50V, 7A, 80W, 100MHz	18j	Mat	2SA1141, 2SA1146, 2SA1186
2SA1186	Si-P	NF/S-L, 150V, 10A, 100W, 60MHz	18j	Sak	2SA1227A, 2SA1386(A)
2SA1187	Si-P	=2SA1186: 12A, 120W	20j	Sak	2SA1078, 2SA1095, 2SA1215, 2SA1186(A), ++
2SA1188	Si-P	Uni, 90V, 0,1A, 0,4W, 130MHz	7c	Hit	2SA970, 2SA1049, 2SA1136, 2SA1285(A), ++
2SA1189	Si-P	=2SA1188: 120V	7c	Hit	2SA970, 2SA1049, 2SA1136, 2SA1295(A), ++
2SA119	Si-P	HF-Tr, 40V, 0,3A, 0,65W, 200MHz	2a	Fui	BC303..304, BSW23, 2N2904..2905(A), ++

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2SA1190	Si-P	=2SA1188. ra	7c	Hit	2SA872, 2SA970, 2SA1049, 2SA1136,++
2SA1191	Si-P	=2SA1188. ra, 120V	7c	Hit	2SA872A, 2SA970, 2SA1049, 2SA1136,++
2SA1193(K)	Si-P-Darl	Uni, 90V, 1A, 0,9W, B>2000	5c(B)	Hit	BC876, BC878, BC880, BSR60..62, 2SB1405+
2SA1194(K)	Si-P-Darl	Uni-L, 80V, 1A, 8W, B>1000	14b(B)	Hit	BD878, BD778, BD878, BDX45..47,++
2SA1195	Si-P	TV-NF-E, 160V, 1,5A, 15W, 50MHz	18j	Tos	(2SA968(A,B), 2SA1011, 2SA1332,++)
2SA1196	Si-P	S-L, 400V, 0,1A, 10W	30j	Hit	2SA1700, (BF891, 2SA1354, 2SB1011)
2SA1197	Si-P-Darl	=2SA1194	30j	Hit	2SB963..994
2SA1198(S)	Si-P	Uni, 60V, 0,05A, 0,4W, 140MHz	7c,41c	Rhm	BC556, 2SA872(A), 2SA970, 2SA1285,++
2SA1199(S)	Si-P	Uni, 50V, 0,7A, 0,4W, 100MHz	7c,41c	Rhm	BC327, BC638, 2SB647, 2SB910, 2SB1116,++
2SA12	Ge-P	AM-ZF, 16V, Ueb=0,5V, 15mA, 8MHz	2a	Hit	AF124..127, AF200, 2SA201..202
2SA120	Si-P	HF-Tr, 25V, 0,3A, 0,65W, 200MHz	2a	Fui	BC303..304, BSW23, 2N2904..2905(A),++
2SA1200	Si-P	SMD, Uni, 150V, 0,05A, 120MHz	39b	Tos	2SB807, 2SB1046..1047
2SA1201	Si-P	SMD, Uni, 120V, 0,8A, 120MHz	39b	Tos	2SB806, 2SB1025
2SA1202	Si-P	SMD, Uni, 60V, 0,4A, 120MHz	39b	Tos	2SA1368, 2SB787, 2SB789(A)
2SA1203	Si-P	SMD, Uni, 30V, 1,5A, 120MHz	39b	Tos	2SA1213, 2SA1663, 2SB1123, 2SB1313,++
2SA1204	Si-P	SMD, Uni, 35V, 0,8A, 120MHz	39b	Tos	BCX51..53, 2SA1364, 2SB1734, 2SB804,++
2SA1205	Si-P	NF/S-L, 70V, 12A, 100W, 20MHz	13j	Sak	BD246A, BD746A, BDV94, 2SA1292,++
2SA1206	Si-P	S, 15V, 0,05A, 0,6W, <20/40ns	7e	Nec	BSX36, 2N4313, 2N5056..57
2SA1207	Si-P	Uni, 180V, 0,07A, 0,6W, 150MHz	7c	Say	BF436..437, BF423A, 2SA1281,++
2SA1208	Si-P	Uni, 160V, 0,07A, 0,9W, 150MHz	7c(9mm)	Say	BF436, BF423A, 2SA1281..2SA1370..71
2SA1209	Si-P	Uni-L, 160V, 0,14A, 10W, 150MHz	14h	Say	BF416, BF418, 2SA1352, 2SA1407
2SA120A	Si-P	=2SA120: 40V	2a		BC303..304, BSW23, 2N2904..2905(A),++
2SA121	Ge-P	FM, 15V, 2mA, 100MHz	≈2a	Son	AF124..125, AF106, AF306, 2SA340..342
2SA1210	Si-P	Uni-L, 200V, 0,14A, 10W	14h	Say	BF416, BF418, 2SA1352, 2SA1407,++
2SA1211	Si-P	S, 35V, 0,1A, 0,2W, 400MHz	41c	Tos	BC213, BC306, BC556, 2N2906..07,++
2SA1213	Si-P	SMD, Uni, 50V, 2A, 120MHz	39b	Tos	2SA1417, 2SB1029, 2SB1123, 2SB1313,++
2SA1214	Si-P	NF/HF/S-L, 60V, 2A, 25W, 35MHz	14h	Tos	BD178, BD236, BD440, 2SB1217,++
2SA1215	Si-P	NF/S-L, 160V, 15A, 150W, 50MHz	20j	Sak	2SA1076, 2SA1095, 2SA1166(A), 2SA1369,++
2SA1216	Si-P	NF/S-L, 180V, 17A, 200W, 40MHz	20j	Sak	2SA1170, 2SA1295
2SA1217	Si-P	NF-L, 40V, 3A, 10W, 100MHz	14h	Tos	BD788, 2SB744(A), 2SB986,++
2SA1218	Si-P	S, 60V, 0,6A, 0,36W, <45/300ns	2a	Nec	BSW24, 2N2906..07(A), 2N4026..29
2SA1219	Si-P	Uni, 60V, 0,1A, 0,25W, 160MHz	40c	Nec	BC212, BC256, BC266, BC556,++
2SA122	Ge-P	FM, 15V, 2mA, 100MHz	≈2a	Son	AF124..125, AF108, AF306, 2SA340..342
2SA1220	Si-P	NF/HF-L, 120V, 1,2A, 20W, 175MHz	14h	Nec	2SA1249, 2SB649
2SA1220A	Si-P	=2SA1220: 160V	14h		2SA1249, 2SB649
2SA1221	Si-P	Uni, 160/140V, 0,5A, 1W, 45MHz	9b	Nec	2N5401, 2SA1013, 2SA1319
2SA1222	Si-P	=2SA1221: 160/160V	9b	Nec	2N5401, 2SA1013, 2SA1319
2SA1223	Si-P	UHF, 20V, 0,05A, 4GHz	25s	Nec	BFQ32, BFQ79, 2SA801, 2SA1057
2SA1224	Si-P	S, UHF, 40V, 0,25A, 2,5GHz	2g	Nec	—
2SA1225	Si-P	NF/S-L, 160V, 1,5A, 15W, 100MHz	30j	Tos	2SA1552, 2SB640..842, 2SB1275
2SA1226	Si-P	SMD, HF, 40V, 30mA, 400MHz	35a	Nec	BF536, BF550, BF568..569, BF880
2SA1227	Si-P	NF-L, 140/140V, 12A, 120W, 60MHz	16j	Nec	2SA1368(A), 2SB617
2SA1227A	Si-P	=2SA1227: 160/180V	16j		2SA1368(A), 2SB617
2SA1228	Si-P	UHF, 20V, 0,05A, 4GHZ	5g	Nec	BFQ24
2SA1229	Si-P	Dual, UHF, 20V, 0,05A, 4GHZ		Nec	2SA1231
2SA123	Ge-P	FM, 15V, 2mA, 100MHz	≈2a	Son	AF124..125, AF108, AF306, 2SA340..342
2SA1230	Si-P	UHF, 15V, 0,05A, 8GHZ	52s	Nec	—
2SA1231	Si-P	Dual, UHF, 15V, 0,05A, 8GHz		Nec	—
2SA1232	Si-P	NF/S-L, 130V, 10A, 100W, 60MHz	16j	Nec	2SA1146, 2SA1186, 2SA1227(A), 2SA1388(A)
2SA1233	Si-P	S-L, 400V, 0,1A, 10W	30j	Hit	2SA1700, (2SA1354, 2SB1011)
2SA1234	Si-P	UHF, 20V, 0,05A	52s	Nec	—
2SA1235	Si-P	SMD, Uni, 50V, 0,2A, 200MHz	35s	Mit	BC856..857, BCW69..70, BCW89
2SA1236	Si-P	S-L, 400V, 2A, 15W	17j	Fui	2SA1009A, 2SA1397
2SA1237	Si-P	Dual, 55V, 0,15A, 0,5W, 100MHz		Say	—
2SA1238	Si-P	Dual, 55V, 0,15A, 0,5W, 100MHz		Say	—
2SA1239	Si-P	Dual, 130V, 0,05A, 0,5W, 110MHz		Say	—
2SA124	Ge-P	FM, 15V, 2mA, 120MHz	≈2a	Son	AF124..125, AF106, AF306, 2SA340..342
2SA1240	Si-P	Dual, 130V, 0,05A, 0,5W, 160MHz		Say	—
2SA1241	Si-P	NF/S-L, lo-sat, 50V, 2A, 10W, 100MHz	30j	Tos	2SB1201..02, 2SB1215..16
2SA1242	Si-P	S-L, 35V, 5A, 10W, 170MHz	30j	Tos	2SA1244, 2SA1401, 2SB1203..1204
2SA1243	Si-P	NF/S-L, 30V, 3A, 15W, 100MHz	30j	Tos	2SB906, 2SB962, 2SB1184, 2SB1202..03,++
2SA1244	Si-P	NF/S-L, lo-sat, 60V, 5A, 20W, 60MHz	30j	Tos	2SA1385, 2SA1795, 2SB1203..04
2SA1245	Si-P	SMD, UHF, 15V, 0,03A, 4GHz	35a	Tos	BFT92..93
2SA1246	Si-P	hi-Ueb, 60V, 0,15A, 0,4W, 100MHz	7c	Say	2SA1253, (BC212, BC256, BC268, BC556)
2SA1247	Si-P	SMD, Uni, 120V, 0,05A, 100MHz	35a	Nec	2SA1312, 2SA1566
2SA1246	Si-P	TV-NF-E, 180/160V, 0,7A, 10W, 120MHz	14h	Say	2SA1249, 2SB649

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2SA1249	Si-P	TV-NF-E, 180/160V, 1,5A, 10W, 120MHz	14h	Say	2SB649
2SA125	Ge-P	FM, 15V, 2mA, 120MHz	≈2a	Son	AF124..125, AF106, AF306, 2SA340..342
2SA1250	Si-P	S-L, 200V, 8A, 30W	22a	Fui	—
2SA1251	Si-P	S, 400V, 0,15A, 0,35W, <300/2300ns	2a	Fui	2SA1625, 2SB1074, 2SB1488
2SA1252	Si-P	SMD, hi-Ueb, 60V, 0,15A, 100MHz	35a	Say	2SA1434, (BC856, BCW69, 2SA1312)
2SA1253	Si-P	hi-Ueb, 60V, 0,2A, 0,25W, 100MHz	40c	Say	2SA1246, (BC212, BC256, BC266, BC556)
2SA1254	Si-P	Uni, 30V, 0,03A, 0,4W, 300MHz	9c	Mat	BC306, BC558, BF324, BF414, BF939,+
2SA1255	Si-P	SMD, Uni, 200V, 0,05A, 100MHz	35a	Tos	FBF821, BF823, BFN23, 2SA1330
2SA1256	Si-P	SMD, FM, 30V, 30mA, 230MHz	35a	Say	BF536, BF550, BF568, BF660
2SA1257	Si-P	SMD, S, NF-Tr, 160V, 0,08A, 130MHz	35a	Say	BFN25, BFN27, 2SA1330
2SA1258	Si-P-Darl+Di	NF/S-L, 70V, 3A, 20W, 200MHz, B=5000	17j	Say	(BDT60A..C, BDW64B..D, 2SB751A..B)
2SA1259	Si-P-Darl+Di	NF/S-L, 70V, 5A, 30W, 200MHz, B=5000	17j	Say	(BDW24B..C, BDW64B..D, 2SB1339)
2SA126	Ge-P	S, 12V, 0,05A, 50/110ns	2a	Nec	ASZ21, 2N2955..2957
2SA1260	Si-P-Darl+Di	NF/S-L, 70V, 7A, 40W, B=5000	17j	Say	BDT62A..C, BDX34B..D
2SA1261	Si-P	S-L, 100V, 10A, 60W, <0,5/2µs	15j	Nec	BD712, BD744C, BD912
2SA1262	Si-P	NF/S-L, lo-sat, 60V, 4A, 30W, 15MHz	17j	Sak	2SB920L, (BD536, BD540A, BD950,++)
2SA1263	Si-P	NF-HiFi-E, 60V, 6A, 60W, 30MHz	18j	Tos	BD246B, BDV94, 2SA1146, 2SA1186,++
2SA1264	Si-P	=2SA1263: 120V, 8A, 60W	18j	Tos	BD246C, 2SA1141, 2SA1186, 2SA1227(A),++
2SA1265	Si-P	=2SA1263: 140V, 10A, 100W	18j	Tos	BD246D, 2SA1146, 2SA1186, 2SA1227(A),++
2SA1266	Si-P	Uni, ra, 50V, 0,15A, 0,4W, 130MHz	7c	Kec	BC416, BC560, 2SA970, 2SA1136..1137,++
2SA1267	Si-P	=2SA1266: 0,2W	41c	Kec	BC416, BC560, 2SA970, 2SA1136..1137,++
2SA1268	Si-P	Uni, ra, 120V, 0,1A, 0,3W, 100MHz	7c	Kec	2SA970, 2SA1049, 2SA1038, 2SA1136,++
2SA1269	Si-P	=2SA1268: 0,2W	41c	Kec	2SA970, 2SA1049, 2SA1038, 2SA1136,++
2SA127	Ge-P	RF/IF AMP, 15V, 50mA, 250MHz	4g	Tos	AF118, SFT162, 2SA358
2SA1270	Si-P	Uni, 35V, 0,5A, 0,5W, 200MHz	7c	Kec	BC327, BC636, 2SA1515, 2SB910,++
2SA1271	Si-P	Uni, 35V, 0,8A, 0,6W, 120MHz	7c	Kec	BC327, BC636, 2SB909..910, 2SB734,++
2SA1272	Si-P	=2SA1271: 0,3W	41c	Kec	BC327, BC636, 2SB909..910, 2SB734,++
2SA1273	Si-P	NF-Tr/E, 30V, 2A, 1W, 120MHz	7c(9mm)	Kec	2SB992, 2SB927, 2SB1312, 2SA1382
2SA1274	Si-P	NF-Tr/E, 60V, 0,4A, 0,8W, 100MHz	7c(9mm)	Kec	BC640, 2N5400..5401, 2SA965, 2SA1533,++
2SA1275	Si-P	NF-Tr/E, 160V, 1A, 0,9W, 50MHz	7c(9mm)	Kec	2SA1013, 2SB1212
2SA1276	Si-P	NF/S-L, 30V, 3A, 10W, 100MHz	17j	Kec	2SA473, 2SA1012, 2SA1288..1289
2SA1277	Si-P	NF/S-L, 30V, 3A, 20W, 100MHz	≈15j	Tos	2SA473, 2SA1012, 2SA1288..1289
2SA1278	Si-P	NF/S-L, 160V, 1,5A, 25W, 100MHz	≈15j	Tos	2SA968(A..B), 2SA1011, 2SA1079, 2SA1332
2SA1279	Si-P	lo-sat, 60V, 5A, 25W, 60MHz	≈15j	Tos	2SA1012, 2SA1289..91, 2SA1293
2SA128	Ge-P	S, 30V, 1A, 0,17W, >15MHz, β>15	3a	Tos	ASY76..77
2SA1280	Si-P	TV-VA-E, 150V, 1,5A, 25W, 4MHz	≈15j	Tos	2SB608, 2SB628(A), 2SB861, 2SB991,++
2SA1281	Si-P	Uni, 160V, 0,1A, 0,9W, 130MHz	7c(9mm)	Mit	BF436, BF423A, 2SA1370
2SA1282(A)	Si-P	Uni, 20V, 2A, 0,9W, 60MHz	7c(9mm)	Mit	2SA1382, 2SB736..739, 2SB892, 2SB1312,++
2SA1283	Si-P	Uni, 60V, 1A, 0,9W, 65MHz	7c(9mm)	Mit	2SA1315, 2SB647, 2SB692, 2SB1041,++
2SA1284	Si-P	Uni, 100V, 0,5A, 0,9W, 130MHz	7c(9mm)	Mit	BC640, 2N5400..5401, 2SA695, 2SB1297,++
2SA1285	Si-P	Uni, 120V, 0,1A, 0,9W, 200MHz	7c(9mm)	Mit	2SA1281, 2SA1124, 2SA1482
2SA1285A	Si-P	=2SA1285: 150V	7c(9mm)		2SA1124, 2SA1281, 2SA1482
2SA1286	Si-P	hi-beta, lo-sat, 30V, 1,5A, 0,9W, B>400	7c(9mm)	Mit	(2SB692, 2SB927)
2SA1287	Si-P	lo-sat, 50V, 1A, 0,9W, 90MHz, B>400	7c(9mm)	Mit	(2SA1315, 2SB892, 2SB1229)
2SA1288	Si-P	NF/S-L, 80V, 3A, 30W, 100MHz	17j	Say	MJE15029, 2SA1293
2SA1289	Si-P	NF/S-L, lo-sat, 60V, 5A, 30W, 100MHz	17j	Say	2SA1293
2SA129	Ge-P	=2SA128: β>35	3a	Tos	ASY76..77
2SA1290	Si-P	NF/S-L, lo-sat, 60V, 7A, 35W, 100MHz	17j	Say	2SA1329
2SA1291	Si-P	NF/S-L, lo-sat, 60V, 10A, 40W, 100MHz	17j	Say	2SA1329
2SA1292	Si-P	NF/S-L, lo-sat, 60V, 15A, 70W, 100MHz	18j	Say	(2SB922L)
2SA1293	Si-P	lo-sat, 100V, 5A, 30W, 60MHz	17j	Tos	—
2SA1294	Si-P	NF/S-L, 230V, 15A, 130W, 35MHz	18j	Sak	—
2SA1295	Si-P	NF/S-L, 230V, 17A, 200W, 35MHz	20j	Sak	—
2SA1296	Si-P	Uni, 20V, 2A, 0,75W, 120MHz	7c	Tos	2SA1315, 2SA1382, 2SB985, 2SB911,++
2SA1297	Si-P	=2SA1296: 0,4W	41c	Tos	2SA1315, 2SA1362, 2SB985, 2SB911,++
2SA1298	Si-P	SMD, Uni, 30V, 0,8A, 120MHz	35a	Tos	BCW67..68, 2SA1621
2SA1299	Si-P	Uni, ra, 50V, 0,2A, 0,3W, 200MHz	41c	Mit	BC416, BC560, 2SA970, 2SA1136..1137,++
2SA12H	Ge-P	=2SA12: Ueb=12V	2a		—
2SA13	Ge-P	AM-ZF, 12V, 15mA, 8MHz	2a	Hit	AF124..127, AF200, 2SA201..202
2SA130	Ge-P	RF/IF AMP, 20V, 10mA, 400MHz	4g	Hit	AF124..126, AF200, 2SA218..227
2SA1300	Si-P	Uni, lo-sat, 20V, 2A, 0,75W, 140MHz	7c	Tos	2SB926..927, 2SB892, 2SB1229
2SA1301	Si-P	HiFi-NF-E, 160V, 12A, 120W, 30MHz	77j	Tos	2SA1553, 2SB1153, 2SB1162..63, 2SB1347++
2SA1302	Si-P	HiFi-NF-E, 200V, 15A, 150W, 30MHz	77j	Tos	2SA1553
2SA1303	Si-P	NF/S-L, 150V, 14A, 125W, 50MHz	18j	Sak	2SA1227A, 2SA1386(A), 2SB617
2SA1304	Si-P	TV-VA, NF/S-L, 150V, 1,5A, 20W, 4MHz	17c	Tos	2SA1306, 2SA1332, 2SA1606, 2SB1338,++
2SA1305	Si-P	NF/S-L, 30V, 3A, 15W, 100MHz	17c	Tos	2SA1307, 2SB1185, 2SB1274

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2SA1306	Si-P	NF/S-L, 160V, 1,5A, 20W, 100MHz	17c	Tos	2SA1332, 2SA1606, 2SB1186A
2SA1306A	Si-P	=2SA1306: 180V	17c		2SA1606
2SA1306B	Si-P	=2SA1306: 200V	17c		—
2SA1307	Si-P	DC-DC-Con, Io-sat, 60V, 5A, 20W, 60MHz	17c	Tos	2SA1388, 2SA1469..70, 2SA1441
2SA1306	Si-P	S-L, Io-sat, 100V, 5A, 30W, 80MHz	≈15j	Tos	2SA1293
2SA1309	Si-P	Uni, 30V, 0,1A, 0,3W, 60MHz	40c	Mat	BC213, BC258, BC306, BC558, ++
2SA1309A	Si-P	=2SA1309: 60V	40c		BC212, BC257, BC307, BC557, ++
2SA131	Ge-P	RF/IF AMP, 15V, 50mA, 250MHz	2a	Hit	AF124..126, AF200, 2SA218..227
2SA1310	Si-P	Uni, ra, 60V, 0,1A, 0,3W, 200MHz	40c	Mat	BC418, BC580, 2SA970, 2SA1136..1137, ++
2SA1311	Si-P	SMD, Uni, ra, 60V, 0,15A, 150MHz	35a	Tos	2SA1312
2SA1312	Si-P	SMD, Uni, ra, 120V, 0,1A, 100MHz	35a	Tos	2SB792
2SA1313	Si-P	SMD, Uni, 50V, 0,5A, 200MHz	35a	Tos	BC607, BCX17, 2SA1388
2SA1314	Si-P	SMD, Io-sat, 20V, 2A, 140MHz	39b	Tos	2SB1121..23
2SA1315	Si-P	Uni, Io-sat, 60V, 2A, 0,9W, 80MHz	7c(9mm)	Tos	2SB1459
2SA1318	Si-P	Uni, ra, 60V, 0,1A, 0,4W, 50MHz	7c	Tos	2SA970, 2SA1038, 2SA1049, 2SA1136..37, ++
2SA1317	Si-P	Uni, 60V, 0,2A, 0,3W, 200MHz	40c	Say	BC212, BC258, BC266, BC558, ++
2SA1318	Si-P	=2SA1317: 0,5W	7c	Say	BC212, BC258, BC266, BC558, ++
2SA1319	Si-P	Uni, 160V, 0,7A, 0,7W, 120MHz	7c	Say	2SA1766
2SA132	Ge-P	RF/IF AMP, 15V, 50mA, 250MHz	2a	Hit	AF124..126, AF200, 2SA218..227
2SA1320	Si-P	Vid, 250V, 0,05A, 0,6W, 60MHz	7c	Tos	BF423, BF436..437, 2SA1371..1372, ++
2SA1321	Si-P	=2SA1320: 0,9W	7c(9mm)	Tos	BF423, BF436..437, 2SA1371..1372, ++
2SA1322	Si-P	-2SA320: 5W	14h	Tos	BF416, BF418, BF470, BF472, ++
2SA1323	Si-P	Uni, 30V, 0,03A, 0,3W, 300MHz	40c	Mat	BC308, BC558, BF324, BF414, BF939, +
2SA1324	Si-P	SMD, Uni, 50V, 0,15A, >80MHz	35d	Tos	BC856R..857R, BCW69..70R, BCW69R, ++
2SA1325	Si-P	SMD, Uni, 120V, 0,1A, 100MHz	35d	Tos	(2SA1312)
2SA1326	Si-P	SMD, Uni, 35V, 0,5A, 200MHz	35d	Tos	BC807R, BCW68R, BCX17R, (2SA1313)
2SA1327	Si-P	Io-sat, 50V, 10A, 20W, 50MHz	17c	Tos	2SA1471, 2SA1587..88
2SA1328	Si-P	DC-DC-Con, Io-sat, 60V, 12A, 40W, 70MHz	17j	Tos	2SB903
2SA1329	Si-P	=2SA1328: 80V, 50MHz	17j	Tos	2SA1329
2SA133	Ge-P	RF/IF AMP, 15V, 50mA, 250MHz	2a	Hit	AF124..127, AF200, 2SA218..227
2SA1330	Si-P	SMD, S, 200V, 0,1A, 120MHz, 150/1500ns	35a	Nec	BFN25, BFN27
2SA1331	Si-P	SMD, S, 60V, 0,15A, 100MHz, 160/390ns	35a	Say	BC858, BCW89, BSR15..16, 2SA1338, ++
2SA1332	Si-P	NF/S-L, 160V, 1,5A, 20W, 200MHz	17c	Tos	2SA1306(A,B), 2SA1606
2SA1333	Si-P	NF/S-L, 200V, 15A, 150W, 30MHz	20j	Tos	2SA1189..1170, 2SA1295, 2SB758
2SA1334	Si-P	Uni, 30V, 0,8A, 0,6W, 120MHz	7c	Tos	BC327..328, BC636, 2SB909..910, ++
2SA1335	Si-P	Uni, ra, 120V, 0,1A, 0,2W, 100MHz	41c	Tos	2SA970, 2SA1036, 2SA1049, 2SA1136..37, ++
2SA1338	Si-P	Uni, 20V, 2A, 0,7W, 80MHz	7c	Mit	MPS750, 2SA1382, 2SB736..739, 2SB892, ++
2SA1337	Si-P	Uni, 55V, 0,1A, 0,3W, 200MHz	40c	Hit	BC212, BC257, BC307, BC557, ++
2SA1338	Si-P	=2SA1339: SMD	35a	Say	BSR15..16, BSS60, BSS82
2SA1339	Si-P	S, 60V, 0,5A, 0,3W, 200MHz, 70/450ns	40c	Say	BSW24, 2N2906..07(A), 2N4026..29, ++
2SA134	Ge-P	FM, 20V, 10mA, 140MHz	1g	Hit	AF124..125, AF106, AF306, 2SA213..216
2SA1340	Si-P	Uni, 55V, 0,1A, 0,4W, 200MHz	9c	Hit	BC212, BC257, BC307, BC557, ++
2SA1341	Si-P+R	=2SA1345: SMD	35a	Say	DTA144EK, FN1L4M, RN2404, UN2113, ++
2SA1342	Si-P+R	=2SA1346: SMD	35a	Say	DAT144EK, FN1F4M, RN2403, UN2112, ++
2SA1343	Si-P+R	=2SA1347: SMD	35a	Say	DTA144WK, FN1L4L, RN2409, UN211E, ++
2SA1344	Si-P+R	=2SA1348: SMD	35a	Say	DTA114EK, FN1A4M, RN2402, UN2111, ++
2SA1345	Si-P+R	S, Rb=Rbe=47kΩ, 50V, 0,1A, 200MHz	40c	Say	AN1L4M, DTA144ES, RN2004, UN4113, ++
2SA1346	Si-P+R	S, Rb=Rbe=22kΩ, 50V, 0,1A, 200MHz	40c	Say	AN1F4M, DTA124ES, RN2003, UN4112, ++
2SA1347	Si-P+R	S, Rb=46kΩ, Rbe=23kΩ, 50V, 0,1A, 200MHz	40c	Say	AN1L4L, DTA144WS, RN2009, UN411E, ++
2SA1348	Si-P+R	S, Rb=Rbe=10kΩ, 50V, 0,1A, 200MHz	40c	Say	AN1A4M, DTA114ES, RN2002, UN4111, ++
2SA1349	Si-P	Dual, 80V, 0,1A, 0,4W, 170MHz	7-SIP	Tos	—
2SA135	Ge-P	FM, 20V, 10mA, 150MHz	1g	Hit	AF124..125, AF106, AF306, 2SA213..216
2SA1350	Si-P	Uni, 40V, 0,1A, 0,3W, 200MHz	41c	Hit	BC212, BC257, BC307, BC557, ++
2SA1351	Si-P	=2SA1350: 0,4W	9c	Hit	BC212, BC257, BC307, BC557, ++
2SA1352	Si-P	Vid, hi-def, 200V, 0,1A, 5W, 70MHz	14h	Say	2SA1390..81, 2SA1406..07
2SA1353	Si-P	=2SA1352: 300V	14h	Say	2SA1361, (BF418)
2SA1354	Si-P	=2SA1352: 400V	14h	Say	(2SB1011)
2SA1355	Si-P	NF/S-L, 70V, 4A, 30W, 40MHz	17j	Sak	BD244A, BD538, BD540B, 2SA1269, ++
2SA1356	Si-P	Io-sat, 40V, 0,8A, 5W, 100MHz	14b	Tos	2SB1144, (BD136, BD227, BD376, ++)
2SA1357	Si-P	Io-sat, 35V, 5A, 10W, 170MHz	14b	Tos	(2SA1120)
2SA1358	Si-P	NF-L, 120V, 1A, 10W, 120MHz	14b	Tos	2SB1144, (2SA1178, 2SA1184, 2SA1220(A))
2SA1359	Si-P	NF/S-L, 40V, 3A, 10W, 100MHz	14b	Tos	2SB1143, (BD786, MJE250..252, 2SA1217)
2SA136	Ge-P	AM-VM/O, 6V, 10mA, 10MHz	2a	Fui	AF124..126, AF200, 2SA218..227
2SA1360	Si-P	NF-L, 150V, 0,05A, 5W, 200MHz	14b	Tos	2SA1477..78, 2SA1540, (BF418, BF470++)
2SA1361	Si-P	S/Vid-L, 250V, 0,05A, 60MHz	14b	Tos	2SA1479..80, (BF416, BF418, BF470, ++)
2SA1382	Si-P	SMD, Uni, 15V, 0,8A, 120MHz	35a	Tos	BCW87..66, 2SA1298

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2SA1363	Si-P	SMD, lo-sat, 20V, 2A, 80MHz	39b	Mit	2SA1314, 2SA1369, 2SB1121
2SA1364	Si-P	SMD, lo-sat, 80V, 1A, 85MHz	39b	Mit	2SA1681, 2SB1115, 2SB1122..1123,++
2SA1365	Si-P	SMD, Uni, 25V, 0,7A, 180MHz	35a	Mit	BCW67..68, 2SA1298, 2SA1621
2SA1366	Si-P	SMD, Uni, 55V, 0,4A, 150MHz	35a	Mit	BCW68, BCX42, 2SB1198
2SA1367	Si-P	Uni, 50V, 0,1A, 0,3W, 100MHz	41c	Mit	BC212, BC257, BC307, BC557,++
2SA1368	Si-P	SMD, Uni, 100V, 0,5A, 130MHz	39b	Mit	2SA1201, 2SB789(A), 2SB805..806
2SA1369	Si-P	SMD, lo-sat, 30V, 1,5A, 90MHz, B>400	39b	Mit	(2SA1314, 2SB1121)
2SA137	Ge-P	AM-ZF, 6V, 10mA, 5MHz	2a	Fui	AF124..127, AF200, 2SA218..227
2SA1370	Si-P	Vid, hi-def, 200V, 0,1A, 1W, 150MHz	7c(9mm)	Say	(BF423A, BF436..437, 2SA1024, 2SA1251)
2SA1371	Si-P	=2SA1370: 300V	7c(9mm)		(BF421A, BF437, 2SA1024, 2SA1251)
2SA1372	Si-P	=2SA1370: 400V	7c(9mm)		(2SA1251, 2SA1584, 2SA1760)
2SA1373	Si-P	Uni, 60V, 0,2A, 0,4W, 250MHz	7b	Hit	BC212, BC258, BC286, BC556,++
2SA1374	Si-P	Uni, 55V, 0,1A, 0,3W, 250MHz	40c	Hit	BC212, BC256, BC268, BC556,++
2SA1375	Si-P	S/Vid-L, 250V, 0,07A, 10W, 80MHz	30j	Mat	2SA1700, (BF416, BF816, BF848..849++)
2SA1376(A)	Si-P	S/Vid, 200V, 0,1A, 0,75W, 120MHz	7c	Nec	BF423, BF436..437, 2SA1370..1372
2SA1377	Si-P	Uni, 55V, 0,1A, 0,3W, 150MHz	7c	Tos	BC212, BC258, BC268, BC558,++
2SA1378	Si-P	Uni, 35V, 0,5A, 0,3W, 200MHz	41c	Tos	BC327..328, BC636, 2SA1515, 2SB910,++
2SA1379	Si-P	S-L, 600V, 0,8A, 10W	30j	Hit	2SA1413, 2SA1807
2SA138	Ge-P	S, 20V, Ueb=10V, 25mA, 0,06W, 15MHz	2a	Fui	ASY26..27, ASY48
2SA1380	Si-P	Vid-L, hi-def, 200V, 0,1A, 7W, 150MHz	14h	Say	2SC1362..53, 2SA1406..07
2SA1381	Si-P	=2SA1380: 300V	14h	Say	2SA1353..54
2SA1382	Si-P	Uni, 50V, 2A, 0,9W, 110MHz	7c(9mm)	Tos	2SA1315, 2SB892, 2SB1312
2SA1383	Si-P	NF-L, 180V, 0,1A, 10W, 180MHz	17j	Nec	2SA1476, (BF616, BF848..849, BF760++)
2SA1384	Si-P	Vid, 300V, 0,1A, 70MHz	39b	Tos	BFN19
2SA1385	Si-P	NF/S-L, 80V, 5A, 10W	30j	Nec	2SA1244, 2SA1401, 2SB1203..04, (BD244A++)
2SA1386	Si-P	NF/S-L, 180V, 15A, 130W, 40MHz	18j	Sak	2SA1294
2SA1386A	Si-P	=2SA1386: 180V	18j		2SA1294
2SA1387	Si-P	S-L, lo-sat, 80V, 5A, 20W, 80MHz	17c	Tos	2SA1307, 2SA1469, (2SA1293)
2SA1388	Si-P	NF/S-L, lo-sat, 100V, 5A, 25W, 80MHz	17c	Tos	2SA1741..42, (2SA1293)
2SA1389	Si-P	NF/S-L, 180V, 12A, 120W, 30MHz	20j	Tos	2SA1078, 2SA1095, 2SA1168(A), 2SA1215,++
2SA139	Ge-P	S, 20V, Ueb=10V, 50mA, 0,08W, 8MHz	2a	Fui	ASY26..27, ASY48
2SA1390	Si-P	Uni, 35V, 0,5A, 0,3W, 120MHz	40c	Hit	BC327..328, BC636, 2SA1515, 2SB910,++
2SA1391	Si-P	=2SA1392: ra	7c	Say	BC418, BC560, 2SA970, 2SA1136..1137,++,
2SA1392	Si-P	NF, 60V, 0,2A, 0,4W, 200MHz	7c	Say	BC212, BC258, BC268, BC558,++
2SA1393	Si-P	NF/S-L, 120V, 1,5A, 20W, 180MHz	17c	Nec	2SA1306(A,B), 2SA1332, 2SA1606
2SA1394	Si-P	NF/S-L, hi-Ueb, 80V, 5A, 25W	17c	Nec	(2SA1469, 2SB1016, 2SB1294)
2SA1395	Si-P	NF/S-L, 100V, 2A, 15W	17c	Nec	2SA1440, 2SB1095, 2SB1338
2SA1396	Si-P	NF/S-L, 100V, 10A, 30W	17c	Nec	2SA1443, 2SA1652, (BD712, BD744C,++)
2SA1397	Si-P	S-L, 400V, 2A, 15W	17c	Nec	2SA1501, (2SA1009A, 2SA1236)
2SA1398	Si-P	Uni, 25V, 0,7A, 0,9W, 180MHz	7c(9mm)	Mit	2SA968, 2SA1382, 2SB978, 2SB1041
2SA1399	Si-P	Uni, 55V, 0,4A, 0,9W, 150MHz	7c(9mm)	Mit	BC638, 2N5400..01, 2SA965, 2SA1533,++
2SA14	Ge-P	HF/ZF, 16V, 15mA, 4MHz	2a	Hit	AF124..127, AF200, 2SA201..203
2SA1400	Si-P	S-L, 400V, 0,5A, 10W, <1/6µs	30j	Nec	2SA1379, 2SA1413
2SA1401	Si-P	NF/S-L, 80V, 5A, 10W	30j	Nec	2SA1385, 2SB1203..04, 2SB1244, (BD244A++)
2SA1402	Si-P	Vid-E, hi-def, 80V, 0,3A, 8W, 700MHz	14h	Say	2SA1405
2SA1403	Si-P	Vid-E, hi-def, 80V, 0,5A, 10W, 600MHz	14h	Say	—
2SA1404	Si-P	Vid-E, hi-def, 120V, 0,2A, 8W, 500MHz	14h	Say	2SA1405
2SA1405	Si-P	Vid-E, hi-def, 120V, 0,3A, 8W, 500MHz	14h	Say	—
2SA1406	Si-P	Vid-E, hi-def, 200V, 0,1A, 7W, 400MHz	14h	Say	2SA1352, 2SA1407
2SA1407	Si-P	Vid-E, hi-def, 200V, 0,15A, 7W, 400MHz	14h	Say	—
2SA1408	Si-P	CTV-VA, NF-E, 150V, 1,5A, 10W, 50MHz	14b	Tos	2SA1507, (2SA1249, 2SB849)
2SA1409	Si-P	hi-beta, S, 25V, 0,15A, 0,25W, B=1000	7c	Nec	2SA1436, (BC213, BC308, BC558,++)
2SA141	Ge-P	AM-ZF, 15V, 15mA, 4MHz	2a	Mit	AF124..127, AF200, 2SA201..203
2SA1410	Si-P	=2SA1409:	40c	Nec	2SA1436, (BC213, BC308, BC558,++)
2SA1411	Si-P	=2SA1409: SMD	35a	Nec	(BC858..858, BCW29..30, BCW69..70,++)
2SA1412	Si-P	S-L, 400/400V, 2A, 10W, 40MHz	80j	Nec	2SA1773
2SA1413	Si-P	S-L, 600/600V, 1A, 10W, 26MHz	80j	Nec	2SA1379, 2SA1807
2SA1415	Si-P	SMD, Uni, 180V, 0,14A, 150MHz	89b	Say	BFN17, BFN19
2SA1416	Si-P	SMD, Uni, 120V, 1A, 120MHz	89b	Say	2SA1419, 2SB1025..1028
2SA1417	Si-P	SMD, Uni, 120V, 2A, 120MHz	39b	Say	2SA1419, 2SB1027..28
2SA1418	Si-P	SMD, Uni, 180V, 0,7A, 120MHz	39b	Say	2SA1419, 2SB1027..1028
2SA1419	Si-P	SMD, Uni, 180V, 1,5A, 120MHz	39b	Say	2SB1027..28
2SA142	Ge-P	AM-V/M, 15V, 15mA, 8MHz	2a	Mit	AF124..128, AF200, 2SA201..203
2SA1420	Si-P+R	=2SA1345: 0,4W	7c	Say	→2SA1345
2SA1421	Si-P+R	=2SA1346: 0,4W	7c	Say	→2SA1346
2SA1422	Si-P+R	=2SA1347: 0,4W	7c	Say	→2SA1347

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2SA1423	Si-P+R	=2SA1348. 0,4W	7c	Say	→2SA1348
2SA1424	Si-P	SMD, UHF, 20V, 0,05A, 4GHz	35a	Nec	BFT93
2SA1425	Si-P	Uni, 120V, 0,8A, 1W, 120MHz	9c	Tos	2SA965, 2SA1013, 2SA1319, 2SA1768,++
2SA1426	Si-P	Uni, 35V, 0,8A, 1W, 120MHz	9c	Tos	BC327, BC636, 2SB909. 910,++
2SA1427	Si-P	Uni, 30V, 1,5A, 1W, 120MHz	9c	Tos	MPS750, 2SA966, 2SB819, 2SB892, 2SB978++
2SA1428	Si-P	Uni, 50V, 2A, 1W, 100MHz	9c	Tos	MPS750..751, 2SB892, 2SB1433. 34,++
2SA1429	Si-P	Uni, 80V, 2A, 1W, 80MHz	9c	Tos	MPS751, 2SA1315, 2SB1459
2SA142A	Ge-P	=2SA142: 40V	2a		2SA102..104
2SA143	Ge-P	AM-V/M, 15V, 15mA, 15MHz	2a	Mit	AF124..126, AF200, 2SA202
2SA1430	Si-P	Uni, lo-sat, 20V, 2A, 1W, 140MHz	9c	Tos	MPS750, 2SB733, 2SB738..739, 2SB892, ++
2SA1431	Si-P	Uni, 35V, 5A, 1W, 170MHz	9c	Tos	2SB1446
2SA1432	Si-P	Vid, 300V, 0,1A, 1W, 80MHz	9c	Tos	BF421A, BF437, BF493, 2SA1624,++
2SA1433	Si-P	Vid, hi-def, 70V, 0,05A, 0,9W, 700MHz	7c(9mm)	Say	—
2SA1434	Si-P	hi-Ueb, hi-beta, 80V, 0,1A, B>500	35a	Say	—
2SA1435	Si-P	hi-Ueb, hi-beta, lo-sat, 30V, 0,3A, B>500	7c	Say	—
2SA1436	Si-P	hi-Ueb, hi-beta, lo-sat, 80V, 0,2A, B>500	7c	Say	—
2SA1437	Si-P	hi-Ueb, hi-beta, 120V, 0,05A, 85MHz, B>400	7c	Say	—
2SA1439	Si-P	hi-Ueb, hi-beta, 30V, 1,2A, B>500	7c(9mm)	Say	—
2SA1439				Say	,
2SA144	Ge-P	AM-V/M/O/ZF, 15V, Ueb=10V, 10mA, 15MHz	2a	Mat	(AF124..128, AF200, 2SA202)
2SA1440	Si-P	lo-sat, 100V, 3A, 15W, <300/1800ns	17c	Nec	2SA1388, 2SA1441, 2SA1741
2SA1441	Si-P	S-L, 100V, 5A, 25W, <300/1800ns	17c	Nec	2SA1388, 2SA1442, 2SA1741
2SA1442	Si-P	S-L, 100V, 7A, 30W, <300/1800ns	17c	Nec	2SA1443, 2SA1742
2SA1443	Si-P	S-L, 100V, 10A, 30W, <300/1800ns	17c	Nec	2SA1444, 2SA1743
2SA1444	Si-P	S-L, 100V, 15A, 30W, <300/1800ns	17c	Nec	2SA1744
2SA145	Ge-P	AM-V/M/O/ZF, 15V, Ueb=10V, 10mA, 6MHz	2a	Mat	(AF124..126, AF200, 2SA201..203)
2SA1450	Si-P	Uni, 100V, 0,5A, 0,6W, 120MHz	7c	Say	BC640, 2SA965, 2SB847, 2SA1883,++
2SA1451	Si-P	lo-sat, 60V, 12A, 30W, 70MHz, 300/1200ns	17c	Tos	2SA1568, 2SA1771
2SA1452	Si-P	=2SA1451: 80V, 50MHz, 300/1500ns	17c	Tos	2SA1771
2SA1453	Si-P	Uni, 50V, 0,1A, 0,2W, 200MHz	41c	Tos	BC212, BC257, BC307, BC557, ++
2SA1455K	Si-P	SMD, NF, ra, 120V, 0,05A, 140MHz	35a	Rhm	2SA1312, 2SA1587
2SA1458	Si-P	HF/S, 40V, 0,2A, 0,25W, <70/300ns	40c	Nec	2N3250..51, 2N3905..06
2SA1459	Si-P	S, 15V, 0,05A, 0,25W, <20/40ns	40c	Nec	2N4258, 2N4313, 2N5056..57
2SA146	Ge-P	RF/IF AMP, 15V, 50mA, 250MHz	2a	Mit	AF124..127, AF200, 2SA218..227
2SA1460	Si-P	S, 80V, 1A, 1W, <40/100ns	9b	Nec	—
2SA1461	Si-P	=2SA1458: SMD	35a	Nec	—
2SA1462	Si-P	=2SA1459: SMD	35a	Nec	—
2SA1463	Si-P	=2SA1460: SMD	39b	Nec	—
2SA1464	Si-P	SMD, HF/S, 80V, 0,5A, <35/225ns	35a	Nec	—
2SA1465	Si-P	S, 30V, 1A, 0,75W, <1/2µs	7c	Nec	—
2SA1466	Si-P	=2SA1465: 0,35W	40c	Nec	—
2SA1467	Si-P	=2SA1465: SMD	35a	Nec	—
2SA1468	Si-P	SMD, HF/Vid, 180V, 0,1A, 200MHz	35a	Hit	BFN25, 2SA1257, 2SA1330
2SA1469	Si-P	S-L, lo-sat, 80V, 5A, 20W, 100/800ns	17c	Say	2SA1388, 2SA1441, 2SA1741
2SA147	Ge-P	RF/IF AMP, 15V, 50mA, 250MHz	2a	Mit	AF124..126, AF200, 2SA218. 227
2SA1470	Si-P	S-L, lo-sat, 80V, 7A, 25W, 100/600ns	7c	Say	2SA1452, 2SA1442, 2SA1742
2SA1471	Si-P	S-L, lo-sat, 80V, 10A, 30W, <100/900ns	17c	Say	2SA1443, 2SA1743
2SA1474	Si-P	Vid-E, hi-def, 80V, 0,8A, 15W, 800MHz	17j	Say	—
2SA1475	Si-P	Vid-E, hi-def, 120V, 0,4A, 15W, 500MHz	17j	Say	—
2SA1476	Si-P	Vid-E, hi-def, 200V, 0,2A, 15W, 400MHz	17j	Say	—
2SA1477	Si-P	NF-Tr, 180V, 0,14A, 10W, 150MHz	14b	Say	2SA1541, 2SA1801, (BF416, BF418)
2SA1478	Si-P	Vid-E, hi-def, 200V, 0,1A, 5W, 150MHz	14b	Say	2SA1540..41, (2SA1380..81, 2SA1406..07)
2SA1479	Si-P	Vid-E, hi-def, 300V, 0,1A, 7W, 70MHz	14b	Say	(2SA1353, 2SA1381)
2SA146	Ge-P	RF/IF AMP, 15V, 50mA, 250MHz	2a	Mit	AF124..126, AF200, 2SA218. 227
2SA1480	Si-P	Vid-E, hi-def, 300V, 0,1A, 7W, 150MHz	14b	Say	(2SA1353, 2SA1381)
2SA1481	Si-P	S, 80V, 0,15A, 0,25W, <360/1170ns	40c	Say	BC212, BC258, BC558, 2N2906..07,++
2SA1482	Si-P	NF, ra, 150V, 0,05A, 0,85W	7c(9mm)	Rhm	2SA1016K, 2SA1124
2SA1483	Si-P	SMD, Uni, 80V, 0,2A, 200MHz	39b	Tos	—
2SA1484	Si-P	SMD, Uni, 90V, 0,1A, 130MHz	35a	Hit	2SA1312
2SA1485	Si-P	NF, Vid, 200V, 0,1A, 0,2W, 180MHz	7c	Hit	BF421A, BF436..437, 2SB1349,++
2SA1488	Si-P	S-L, 600/600V, 1A, 15W, <500/5500ns	14h	Nec	(2SA1379, 2SA1413)
2SA1487	Si-P	Video-Tr, 85V, 0,05A, 1W, 500MHz	7c(9mm)	Mat	—
2SA1468	Si-P	NF/S-L, lo-sat, 80V, 4A, 25W, 15MHz	17c	Sak	2SA1307, 2SA1469, 2SB1134..1135
2SA1488A	Si-P	=2SA1488: 80V	17c		2SA1469, 2SB1018
2SA1489	Si-P	NF/S-L, 80V, 6A, 80W, 20MHz	18j	Sak	BD246C, BD546C, 2SB888, 2SB776, ++
2SA149	Ge-P	RF/IF AMP, 15V, 50mA, 250MHz	2a	Mit	AF124..126, AF200, 2SA218..227

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2SA1490	Si-P	NF/S-L, 120V, 8A, 80W, 20MHz	18j	Sak	BD246D, BD546D, 2SB688, 2SB816, ++
2SA1491	Si-P	NF/S-L, 140V, 10A, 100W, 20MHz	18j	Sak	BD246D, 2SA1386(A), 2SA1294, 2SB817
2SA1492	Si-P	NF/S-L, 180V, 15A, 130W, 20MHz	18j	Sak	BD250E, 2SA1386A, 2SA1294
2SA1493	Si-P	NF/S-L, 200V, 15A, 150W, 20MHz	20j	Sak	2SA1169..1170, 2SA1333, 2SB756
2SA1494	Si-P	NF/S-L, 200V, 17A, 200W, 20MHz	20j	Sak	2SA1170, 2SA1295
2SA1495	Si-P	S-L, 400/400V, 0,6A, 15W, 15MHz	≈30j	Mat	2SA1400
2SA1496	Si-P+R	=2SA1497: SMD	35a	Say	FN1A4Z, DTA124TK, KSR2110, UN2117, ++
2SA1497	Si-P+R	S, 50V, 0,1A, 0,3W, 200MHz, Rb=10kΩ	40c	Say	AN1A4Z, DTA114TS, RN2011, UN4115, ++
2SA1498	Si-P	=2SA1495: 25W	30j	Mat	—
2SA1499	Si-P	=2SA1495: 25W	17c	Mat	2SA1397, 2SA1614
2SA15	Ge-P	AM-V/M/O, 16V, Ueb=0,5V, 15mA, 12MHz	2a	Hit	AF124..126, AF200, 2SA202
2SA1500	Si-P	S-L, 400/400V, 5A, 40W, 15MHz	17j	Mat	MJE5851..5652
2SA1501	Si-P	=2SA1500: Iso	17c		—
2SA1502	Si-P+R	=2SA1503: SMD	35a	Say	DTA123YK, UN211H
2SA1503	Si-P+R	S, Rb=2,2k, Rbe=10k, 50V, 0,1A, 0,3W, 200MHz	40c	Say	DTA123YS, UN411H
2SA1504	Si-P	SMD, NF, ra, 50V, 0,15A, 130MHz	35b	Kec	—
2SA1505	Si-P	SMD, NF-Tr, 35V, 0,5A, 200MHz	35b	Kec	—
2SA1506	Si-P	SMD, NF, ra, 120V, 0,1A, 100MHz	35b	Kec	—
2SA1507	Si-P	TV-NF-E, 180/160V, 1,5A, 10W, 120MHz	14b	Say	(2SA1249, 2SB649)
2SA1508	Si-P+R	=2SA1509: SMD	35a	Say	DTA144TK, FN1L4Z, KSR2112, UN2110, ++
2SA1509	Si-P+R	S, 50V, 0,1A, 0,3W, 200MHz, Rb=47kΩ	40c	Say	AN1L4Z, DTA144TS, KSR2012, UN4110, ++
2SA151	Ge-P	AM-ZF, 9V, 15mA, 6MHz	2a	Hit	AF124..27, AF200, 2SA201..203
2SA1510	Si-P+R	=2SA1511: SMD	35a	Say	DTA143TK, FN1L3Z, RN2410, UN2116, ++
2SA1511	Si-P+R	S, 50V, 0,1A, 0,3W, 200MHz, Rb=4,7kΩ	40c	Say	AN1L3Z, DTA143TS, RN2010, UN4116, ++
2SA1512	Si-P	=2SA1128: 0,3W	40c	Mat	→2SA1128
2SA1513	Si-P	S-L, Ic-sat, 100V, 15A, 60W, <300/1800ns	18c	Nec	—
2SA1514	Si-P	SMD, Uni, 120V, 0,05A, 140MHz	≈35d	Rhm	2SA1325
2SA1514K	Si-P	=2SA1514	35a		2SA1312, 2SA1566
2SA1515(S)	Si-P	Uni, 40V, 1A, 0,5(S=0,3)W, 150MHz	7c, 41c	Rhm	BC638, 2SB734, 2SB909, 2SB1116, ++
2SA1516	Si-P	HiFi-NF-E, 180V, 12A, 130W, 25MHz	18j	Tos	2SA1294, 2SA1386A, 2SA1492
2SA1517	Si-P	SMD, 120V, 0,1A, 100MHz	35b	Kec	—
2SA1518	Si-P+R	=2SA1522: SMD	35a	Say	DTB114EK, UN2123
2SA1519	Si-P+R	=2SA1523: SMD	35a	Say	DTB143EK, UN2122
2SA152	Ge-P	AM-V/M, 9V, 15mA, 10MHz	2a	Hit	AF124..128, AF200, 2SA201..202
2SA1520	Si-P+R	=2SA1524: SMD	35a	Say	DTB123YK, UN2124
2SA1521	Si-P+R	=2SA1525: SMD	35a	Say	DTB123EK, UN2121
2SA1522	Si-P+R	S, Rb=Rbe=10kΩ, 50V, 0,5A, 0,3W, 200MHz	40c	Say	DTB114ES, RN2224, UN4123, 2SA1528, ++
2SA1523	Si-P+R	S, Rb=Rbe=4,7kΩ, 50V, 0,5A, 0,3W, 200MHz	40c	Say	DTB143ES, RN2223, UN4122, 2SA1527, ++
2SA1524	Si-P+R	S, Rb=2,2k, Rbe=10k, 50V, 0,5A, 0,3W, 200MHz	40c	Say	DTB123YS, RN2227, UN4124, 2SA1528, ++
2SA1525	Si-P+R	S, Rb=Rbe=2,2kΩ, 50V, 0,5A, 0,3W, 200MHz	40c	Say	DTB123ES, RN2222, UN4121, 2SA1528, ++
2SA1526	Si-P+R	=2SA1522: 0,6W	7c	Say	→2SA1522
2SA1527	Si-P+R	=2SA1523: 0,6W	7c	Say	→2SA1523
2SA1528	Si-P+R	=2SA1524: 0,6W	7c	Say	→2SA1524
2SA1529	Si-P+R	=2SA1525: 0,6W	7c	Say	→2SA1525
2SA153	Ge-P	AM-M, 15V, 4mA, 60MHz	2a	Nec	AF124..128, AF200, 2SA218..227
2SA1530	Si-P	SMD, Uni, 50V, 0,1A, 200MHz	35a	Mit	BC856..857, BCW69..70, BCW89, ++
2SA1531	Si-P	=2SA1034:	35a(2mm)	Mat	2SA1603, 2SA1611, 2SA1576
2SA1531A	Si-P	=2SA1035:	35a(2mm)		2SA1603, 2SA1611, 2SA1576
2SA1532	Si-P	=2SA1022:	35a(2mm)	Mat	BC859W..860W
2SA1533	Si-P	Uni, 60V, 0,5A, 1W, 65MHz	7c(9mm)	Mat	2SA985, 2SB987, 2SB1041, 2SB1297, ++
2SA1534	Si-P	Uni, 30V, 1A, 1W, 200MHz	7c(9mm)	Mat	2SA966, 2SB764, 2SB892, 2SB976
2SA1534A	Si-P	=2SA1534: 60V	7c(9mm)		2SA1315, 2SB647, 2SB764, 2SB1041
2SA1535	Si-P	HF/NF-L, 150V, 1A, 15W, 200MHz	17c	Mat	2SA1306(A,B), 2SA1606, 2SA1332
2SA1535A	Si-P	=2SA1535: 160V	17c		2SA1306, 2SA1606, 2SA1859A
2SA1536	Si-P	Vid-E, hi-def, 60V, 0,3A, 8W, 800MHz	14b	Say	(2SA1402)
2SA1537	Si-P	Vid-E, hi-def, 60V, 0,5A, 10W, 700MHz	14b	Say	(2SA1403)
2SA1538	Si-P	Vid-E, hi-def, 120V, 0,2A, 3W, 400MHz	14b	Say	(2SA1404)
2SA1539	Si-P	Vid-E, hi-def, 120V, 0,3A, 8W, 400MHz	14b	Say	(2SA1405)
2SA154	Ge-P	AM-ZF, 15V, 4mA, 50MHz	2a	Nec	AF124..127, AF200, 2SA218..227
2SA1540	Si-P	Vid-E, hi-def, 200V, 0,1A, 7W, 300MHz	14b	Say	2SA1476, (2SA1352, 2SA1406)
2SA1541	Si-P	Vid-E, hi-def, 200V, 0,2A, 7W, 300MHz	14b	Say	(2SA1407)
2SA1542	Si-P	Uni, 60V, 0,15A, 0,3W, 140MHz	7c	Rhm	BC212, BC256, BC556, 2SB725, ++
2SA1543	Si-P	=2SA1542:	9c	Rhm	BC212, BC256, BC556, 2SB725, ++
2SA1544	Si-P	Vid-E, 250V, 0,1A, 0,75W, 300MHz	7c	Nec	BF421A, BF438..437, BF492..493, ++
2SA1545	Si-P	=2SA1544: 1W	9b	Nec	BF421A, BF438..437, BF492..493, ++
2SA1546	Si-P	=2SA1544: 7W	14h	Nec	BF418, 2SA1353, 2SC1381

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2SA1547	Si-P	=2SA933	9c	Rhm	→2SA933
2SA1548	Si-P	=2SA854: 0,3W	9c	Rhm	→2SA854
2SA1549	Si-P-Darl	=2SA790M: Pins=14mm	5c(B)	Rhm	→2SA790
2SA155	Ge-P	AM-ZF, 15V, 4mA, 55MHz	2a	Nec	AF124..127, AF200, 2SA218..227
2SA1550	Si-P	S-L, 400/400V, 0,5A, 15W, 20MHz,	30j	Mat	2SA1400, 2SA1498
2SA1552	Si-P	NF/S-L, 180V, 1,5A, 15W, 120MHz	30j	Say	2SB768, 2SB840..842
2SA1553	Si-P	NF-HiFi-E, 230/230V, 15A, 150W, 25MHz	Tos	Tos	—
2SA1554	Si-P	=2SA785: Pins=14mm	9c	Rhm	→2SA785
2SA1555	Si-P-Darl	=2SA790: Pins=14mm	5c	Rhm	→2SA780
2SA1556	Si-P	=2SA802: Pins=14mm	9c	Rhm	→2SA802
2SA1557	Si-P	=2SA805: Pins=14mm	9c	Rhm	→2SA805
2SA1558	Si-P	=2SA806: Pins=14mm	9c	Rhm	→2SA806
2SA1559	Si-P	=2SA854: 0,3W	9c	Rhm	→2SA854
2SA156	Ge-P	AM-ZF, 15V, 4mA, 55MHz	2a	Nec	AF124..127, AF200, 2SA218..227
2SA1560	Si-P	=2SA881: Pins=14mm	9c	Rhm	→2SA881
2SA1561	Si-P	=2SA933	9c	Rhm	→2SA933
2SA1562	Si-P	hi-Ueb, hi-beta, lo-sat, 30V, 1,2A, B>500	30j	Say	—
2SA1563	Si-P+R	=2SA564: SMD	35a	Say	DTA114YK, FN1A4P, RN2407, UN2114,++
2SA1564	Si-P+R	S, 50V, 0,1A, 0,3W, Rb=10kΩ, Rbe=47kΩ	40c	Say	AN1A4P, DTA114YS, RN2007, UN4114,++
2SA1565	Si-P+R	=2SA1584:	40f	Say	→2SA1564
2SA1566	Si-P	SMD, NF, 120V, 0,1A, 130MHz	35a	Hit	2SA1312, 2SA1566
2SA1567	Si-P	lo-sat, 50V, 12A, 35W, 40MHz	17c	Sak	2SA1451..52, (2SA1444, 2SA1600..01)
2SA1566	Si-P+Di	=2SA1567: 60V, ±12A	17c	Sak	2SA1451..52, (2SA1444, 2SA1600..01)
2SA157	Ge-P	AM-O, 15V, 4mA, 65MHz	2a	Nec	AF124..126, AF200, 2SA218..227
2SA1571	Si-P+R	=2SA1572: SMD	35a	Say	DTA144GK
2SA1572	Si-P+R	S, 50V, 0,1A, 0,3W, Rbe=47kΩ	40c	Say	DTA144GS
2SA1573	Si-P+R	=2SA1574: SMD	35a	Say	DTA124GK
2SA1574	Si-P+R	S, 50V, 0,1A, 0,3W, Rbe=22kΩ	40c	Say	DTA124GS
2SA1575	Si-P	SMD, HF, 200V, 0,1A, 400MHz	39b	Say	BFN17, BFN19
2SA1576	Si-P	=2SA1037:	35a(2mm)	Rhm	2SA1586, 2SA1603, 2SA1622
2SA1577	Si-P	=2SA1036:	35a(2mm)	Rhm	BCX51
2SA1578	Si-P	SMD, Uni, ra, 20V, 0,05A, 140MHz	35a(2mm)	Rhm	2SA1587
2SA1579	Si-P	=2SA1514:	35a(2mm)	Rhm	2SA1609, 2SA1612, 2SB1220
2SA1560	Si-P	SMD, Vid, 70V, 0,05A, 700MHz	35a	Say	—
2SA1581	Si-P+R	=2SA1582: SMD	35a	Say	—
2SA1562	Si-P+R	S, 50V, 0,1A, 200MHz, Rb=2,2kΩ	40c	Say	—
2SA1563	Si-P	SMD, S, 600/550V, 0,1A, <1/4,5µs	39b	Mat	—
2SA1584	Si-P	S, 400/400V, 0,1A, 0,9W, <1/4µs	7c(9mm)	Rhm	2SA1372, 2SA1584, 2SA1780, 2SB1363
2SA1565(S)	Si-P	Uni, lo-sat, 20V, 2A, 0,4W, 240MHz	41c	Rhm	2SB736..739, 2SB822, 2SB892, 2SB911, ++
2SA1588	Si-P	SMD, Uni, ra, 50V, 0,15A, 150MHz	35a(2mm)	Tos	—
2SA1587	Si-P	SMD, Uni, ra, 20V, 0,1A, 100MHz	35a(2mm)	Tos	2SA1578
2SA1588	Si-P	SMD, Uni, 35V, 0,5A, 200MHz	35a(2mm)	Tos	2SA1577
2SA1589	Si-P+R	=2SA1590: SMD	35a	Say	FN1F4Z, DTA124TK, KSR2111, UN2117,++
2SA159	Ge-P	AM-V/M, 15V, 4mA, 55MHz	2a	Nec	AF124..126, AF200, 2SA218..227
2SA1590	Si-P+R	S, 50V, 0,1A, 0,3W, 200MHz, Rb=22kΩ	40c	Say	AN1F4Z, DTA124TS, KSR2011, UN4117,++
2SA1591	Si-P+R	=2SA1590: Rb=4,7kΩ, Rbe=47kΩ	40c	Say	DTA143ZS, KSR2014, RN2006, 2SA1618
2SA1592	Si-P	S-L, 120V, 1A, 10W, 120MHz	30j	Say	2SA1592, 2SB844..845, 2SB959..960,++
2SA1593	Si-P	S-L, 120V, 2A, 15W, 120MHz	30j	Say	2SB1215..16
2SA1594	Si-P	SMD, Uni, 50V, 0,1A, 140MHz	35a(2mm)	Rhm	BC856W..857W, 2SA1576, 2SA1588, ++
2SA1595	Si-P	SMD, Uni, 50V, 0,1A, 140MHz	35a	Rhm	BC856..857, BCW69..70, 2SA1311, ++
2SA1598	Si-P	NF/S, 80V, 2A, 1,2W, <1/4µs	7c(9mm)	Rhm	2SA1315, 2SA1429, 2SB1459
2SA1597	Si-P+R	=2SA1591: SMD	35a	Say	DTA143ZK, KSR2114, RN2406
2SA1598	Si-P	S-L, lo-sat, 60V, 7A, 25W, <300/2000ns	15c	Shi	2SA1442, 2SA1470, 2SA1742
2SA1599	Si-P	S-L, lo-sat, 60V, 10A, 25W, <300/2000ns	15c	Shi	2SA1443, 2SA1471, 2SA1743
2SA15H	Ge-P	=2SA15: Ueb=12V	2a		—
2SA16	Ge-P	AM-VM/O, 12V, 15mA, 12MHz	2a	Hit	AF124..126, AF200, 2SA202
2SA160	Ge-P	AM-V/M, 15V, 4mA, 55MHz	2a	Nec	AF124..126, AF200, 2SA218..227
2SA1600	Si-P	S-L, lo-sat, 60V, 12A, 30W, <300/2000ns	15c	Shi	2SA1451..52, 2SA1568
2SA1601	Si-P	S-L, lo-sat, 60V, 15A, 45W, <300/2000ns	15c	Shi	2SA1444, 2SA1744
2SA1602	Si-P	=2SA1235:	35a(2mm)	Mit	2SA1586, 2SA1622
2SA1603	Si-P	=2SA1530:	35a(2mm)	Mit	2SA1576, 2SA1588, 2SA1611
2SA1604	Si-P	Dual, 60V, 0,5A, 0,4W, 200MHz		Say	—
2SA1605	Si-P	Vid/S, 250/250V, 0,07A, 15W, >50MHz	13j	Mat	(BF616, BF618, BF760..762, BF848,++)
2SA1606	Si-P	NF-L, 180/160V, 1,5A, 15W, 100MHz	17c	Say	2SA1306A,B, 2SA1859A
2SA1607	Si-P	SMD, S, 40V, 0,15A, <40/205ns	35a	Say	—
2SA1608	Si-P	SMD, S, 60V, 0,5A, <35/225ns	35a(2mm)	Nec	—

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2SA1609	Si-P	SMD, Uni, 160V, 0,05A, 60MHz	35a(2mm)	Nec	—
2SA161	Ge-P	VHF/UHF, 20V, 15mA, 500MHz	5g	Son	AF139, AF239(S)
2SA1610	Si-P	SMD, S, 15V, 0,05A, <20/40ns	35a(2mm)	Nec	2SA1763
2SA1611	Si-P	SMD, Uni, 60V, 0,1A, 180MHz	35a(2mm)	Nec	2SB1218A
2SA1612	Si-P	SMD, Uni, 120V, 0,05A, >50MHz	35a(2mm)	Nec	2SA1578..79, 2SB1220
2SA1613	Si-P	SMD, hi-beta, 25V, 0,15A, 200MHz, B>500	35a(2mm)	Nec	—
2SA1614	Si-P	S-L, 400/400V, 0,5A, 25W, 20MHz	17c	Mat	2SA1397, 2SA1499
2SA1615(Z)	Si-P	lo-sat, 30V, 10A, 15W, 160MHz, 60/520ns	30j	Nec	2SA1834
2SA1616	Si-P+R	=2SA1591:	40f	Say	DTA143Z3, KSR2014, RN2006, 2SA1591
2SA1617	Si-P	SMD, Uni, 55V, 0,1A, 260MHz	35a	Hit	BC856..857, BCW69..70, 2SA1311, ++
2SA1618	Si-P	SMD, Dual, 50V, 0,15A, >80MHz	45	Tos	—
2SA1619	Si-P	Uni, 30V, 0,5A, 1W, 200MHz	7c(9mm)	Mat	BC636, 2SA1362, 2SB910, 2SB987, ++
2SA1619A	Si-P	=2SA1619: 60V	7c(9mm)		BC638, 2SA1362, 2SA1705, 2SB910
2SA162	Ge-P	VHF/UHF, 20V, 15mA, 500MHz	5g	Son	AF139, AF239(S)
2SA1620	Si-P	SMD, Uni, 60V, 0,3A, 100MHz	35a	Tos	2SB1198
2SA1621	Si-P	SMD, Uni, 35V, 0,8A, 120MHz	35a	Tos	BCW67..68, 2SB1197
2SA1622	Si-P	SMD, Uni, 55V, 0,15A, 180MHz	35a(2mm)	Say	2SA1586, 2SA1602, 2SA161t
2SA1623	Si-P+R	=2SA1511:	40f	Say	AN1L3Z, DTA143TS, RN2010, UN4116, ++
2SA1624	Si-P	Vid, 300/300V, 0,1A, 0,5W, 70MHz	7c	Say	BF421A, BF436..437, 2SA1371..72, ++
2SA1625	Si-P	NF/S, 400/400V, 0,5A, 0,75W, <1/6µs	7c	Nec	2SB1074, 2SB1488
2SA1626	Si-P	NF/S, 400/400V, 2A, 1W, <0,5/2,7µs	9b	Nec	2SA1768, (2SA1412)
2SA1627	Si-P	NF/S, 600/600V, 1A, 1W, <0,5/5,5µs	9b	Nec	(2SA1379, 2SA1413)
2SA1628	Si-P	SMD, Uni, 30V, 0,1A, 260MHz	35a(2mm)	Hit	BC856W..858W, 2SC1603, 2SB1216(A), ++
2SA1629	Si-P	SMD, Uni, 55V, 0,1A, 230MHz	35a(2mm)	Hit	BC856W..857W, 2SC1603, 2SB1218A, ++
2SA163	Ge-P	VHF/UHF, 20V, 15mA, 500MHz	5g	Son	AF139, AF239(S)
2SA1630	Si-P	=2SA1530: 0,3W	41c	Mit	BC212, BC257, BC307, BC557, ++
2SA1633	Si-P	NF/S-L, 150V, 10A, 100W, 20MHz	16c	Rhm	(BD246D, 2SA1166, 2SA1366, 2SB817, ++)
2SA1634	Si-P	NF/S-L, 60V, 4A, 40W, 12MHz	17j	Rhm	BD244B, BD536, BD540B, BD952, ++
2SA1635	Si-P	=2SA1634: 30W, Iso	17c	Rhm	2SA1394, 2SA1441, 2SB1095, (BD244B, ++)
2SA164	Ge-P	VHF/UHF, 20V, 15mA, 500MHz	5g	Son	AF139, AF239(S)
2SA1640	Si-P	S-L, 30V, 7A, 40W, <1/3,5ns	15j	Nec	2SA1290..91, 2SB896(A), 2SB919
2SA1641	Si-P	S-L, lo-sat, 25V, 8A, 15W, <300/950ns	30j	Say	2SA1615, 2SA1634
2SA1643	Si-P	lo-sat, 50V, 7A, 25W, 75MHz	17c	Sak	2SA1327, 2SA1470..1471
2SA1644	Si-P	lo-sat, 150V, 5A, 30W, <300/1900ns	17j	Nec	2SA1645, 2SA1646
2SA1644Z	Si-P	=2SA1644:	30j		—
2SA1645	Si-P	lo-sat, 150V, 7A, 35W, <300/1900ns	17j	Nec	2SA1646
2SA1645Z	Si-P	=2SA1645:	30j		—
2SA1646	Si-P	lo-sat, 150V, 10A, 40W, <300/1900ns	17j	Nec	—
2SA1646Z	Si-P	=2SA1646:	30j		—
2SA1647	Si-P	lo-sat, 150V, 5A, 18W, <300/1900ns	30j	Nec	—
2SA1648	Si-P	lo-sat, 100V, 5A, 18W, <300/1800ns	30j	Nec	—
2SA1649	Si-P	S-L, 40V, 7A, 18W, <300/1800ns	30j	Nec	2SB1204, (BD544, BD796, BD806, ++)
2SA165	Ge-P	VHF/UHF, 20V, 15mA, 500MHz	5g	Son	AF139, AF239(S)
2SA1650	Si-P	=2SA1644: Iso, 25W	17c	Nec	2SA1651, 2SA1652
2SA1651	Si-P	=2SA1645: Iso, 30W	17c	Nec	2SA1652
2SA1652	Si-P	=2SA1646: Iso, 30W	17c	Nec	—
2SA1653	Si-P+R	=2SA1654: SMD	35a	Say	FN1L3N, DTA143XK, KSR2105, UN211F
2SA1654	Si-P+R	S, 50V, 0,1A, 0,3W, Rb=4,7kΩ, Rbe=10kΩ	40c	Say	AN1L3N, DTA143XS, KSR2005, UN411F
2SA1655	Si-P+R	=2SA1656: SMD	35a	Say	FN1L3M, DTA143EK, RN2401, UN211L, ++
2SA1656	Si-P+R	S, 50V, 0,1A, 0,3W, Rb=Rbe=4,7kΩ	40c	Say	AN1L3M, DTA143ES, RN2001, UN411L, ++
2SA1657	Si-P	NF/S-L, 150V, 1,5A, 20W, 4MHz	17c	Kec	2SA1304, 2SA1306, 2SA1606, 2SB1096, ++
2SA1658	Si-P	NF/S-L, 30V, 3A, 15W, 100MHz	17c	Kec	2SA1305, 2SA1307, 2SA1440, 2SB1274, ++
2SA1659	Si-P	NF/S-L, 160V, 1,5A, 20W, 100MHz	17c	Kec	2SA1306A,B, 2SA1332, 2SA1606, ++
2SA166	Ge-P	VHF/UHF, 20V, 15mA, 500MHz	5g	Son	AF139, AF239(S)
2SA1660	Si-P	SMD, Uni, 150V, 0,05A, 120MHz	39b	Kec	2SA1200, 2SB807
2SA1661	Si-P	SMD, Uni, 120V, 0,8A, 120MHz	39b	Kec	2SA1201, 2SB806, 2SB1025..26
2SA1662	Si-P	SMD, Uni, 80V, 0,4A, 120MHz	39b	Kec	2SA1202, 2SB767
2SA1663	Si-P	SMD, Uni, 30V, 1,5A, 120MHz	39b	Kec	2SA1314, 2SB1121, 2SB1313
2SA1664	Si-P	SMD, Uni, 35V, 0,8A, 120MHz	39b	Kec	BCX51..53, 2SA1204, 2SA1364, 2SA1734, ++
2SA1666	Si-P	SMD, HF/S, 20V, 0,2A, 35/70ns	35a	Hit	—
2SA1667	Si-P	TV-NF-L, 150/150V, 2A, 25W, 20MHz	17c	Sak	2SA1304, 2SA1306, 2SA1606, 2SB1338, ++
2SA1668	Si-P	=2SA1667: 200/200V	17c	Sak	2SA1306B, 2SB1096, 2SB1530
2SA1669	Si-P	SMD, UHF, 20V, 50mA, 3000MHz	35a	Say	BFR194, 2SA1424
2SA167	Ge-P	HF/S, 20V, Ueb=10V, 0,05A, 0,125W, 9MHz	2a	Nec	ASY26..27, ASY46
2SA1670	Si-P	NF/S-L, 60/60V, 8A, 60W, 20MHz	16c	Sak	2SA1603, 2SA1907
2SA1671	Si-P	NF/S-L, 120/120V, 8A, 75W, 20MHz	16c	Sak	2SA1604, 2SA1908

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2SA1672	Si-P	NF/S-L, 140/140V, 10A, 80W, 20MHz	18c	Sak	2SA1805, 2SA1909
2SA1673	Si-P	NF/S-L, 180/180V, 15A, 85W, 20MHz	18c	Sak	(2SA1294, 2SA1386A, 2SA1492, 2SA1516,++)
2SA1674	Si-P	NF, 80V, 1A, 1W, 120MHz	9c	Mat	BC640, 2SB1130, 2SB1236, 2SB1437,++
2SA1876	Si-P+R	SMD, S, 50V, 0,1A, 200MHz, Rb=Rbe=47kΩ	35a(2mm)	Say	DTA144EU
2SA1677	Si-P+R	SMD, S, 50V, 0,1A, 200MHz, Rb=Rbe=22kΩ	35a(2mm)	Say	DTA142EU
2SA1678	Si-P+R	SMD, S, 50V, 0,1A, 200MHz, Rb=Rbe=10kΩ	35a(2mm)	Say	DTA114EU
2SA1679	Si-P	S-L, Io-sat, 80V, 5A, 10W, <300/2000ns	15c	Shi	2SA1307, 2SA1469, 2SA1741
2SA168(A)	Ge-P	=2SA167: 0,175W	2a°	Nec	ASY26..27, ASY48
2SA1680	Si-P	S, Io-sat, 60V, 2A, 0,9W, 100/400ns	7c(9mm)	Tos	2SA1315, 2SA1382, 2SB892, 2SB1312,++
2SA1681	Si-P	=2SA1680: SMD	39b	Tos	2SB1123..1124, 2SB1520
2SA1682	Si-P	SMD, CTV-Vid, 300V, 0,05A, 70MHz	35a	Tos	BF821, BFN27, 2SA1721
2SA1683	Si-P	Io-sat, 100V, 0,5A, 0,3W, 120MHz, 50/580ns	40c	Say	2SA1683, 2SA1708
2SA1684	Si-P	NF/HF-L, 120/120V, 1,5A, 20W, 150MHz	17c	Nec	2SA1306(A,B), 2SA1393, 2SA1332, 2SB1186+
2SA1685	Si-P	SMD, S, 20V, 0,15A, 400MHz	35a(2mm)	Say	2SA1610, 2SA1763
2SA1687	Si-P	SMD, hi-Ueb, 80V, 0,15A, 130MHz	35a(2mm)	Say	(2SA1252)
2SA1688	Si-P	=2SA1256:	35a(2mm)	Say	—
2SA1689	Si-P	Vid, 300V, 0,05A, 0,5W, 70MHz	7c	Say	BF421(A), BF437, 2SA1371, 2SA1624
2SA169	Ge-P	HF/S, 20V, Ueb=10V, 0,05A, 0,125W, 15MHz	2a	Nec	ASY26..27, ASY46
2SA1690	Si-P	SMD, -/400V, 0,1A	39b	Rhm	2SA1740
2SA1692	Si-P	hi-Ueb, hi-beta, Io-sat, 30V, 2A, 110MHz	=14h	Say	—
2SA1693	Si-P	NF-L, 80/80V, 6A, 80W, 20MHz	18j	Sak	BD246B..F, 2SA1264, 2SB775..776,++
2SA1694	Si-P	NF-L, 120/120V, 8A, 80W, 20MHz	18j	Sak	2SA1146, 2SA1168, 2SA1264, 2SB688,++
2SA1695	Si-P	NF-L, Io-sat, 140/140V, 10A, 100W, 20MHz	18j	Sak	(BD246D..F, 2SA1265, 2SA1645, 2SB817)
2SA1696	Si-P	Vid-L, 120V, 0,4A, 400MHz	17c	Say	(2SA1475)
2SA1697	Si-P	Vid-L, 200/200V, 0,2A, 300MHz	17c	Say	(2SA1478)
2SA1688	Si-P	HF, Vid, 300/300V, 0,07A, 1,2W, >50MHz	14h	Mat	BF418, BF472, 2SA1353, 2SA1381
2SA1899	Si-P	S, Tr, 400/400V, 0,2A, 0,6W, 70MHz	7c	Say	2SA1251, 2SA1625, 2SB1074, 2SB1488,++
2SA17	Ge-P	HF-M, S, 12V, Ueb=0,5V, 15mA, 19MHz	2a	Hit	AF124..27, AF200, 2SA100, 2SA102
2SA170	Ge-P	=2SA189: 0,175W	2a°	Nec	ASY26..27, ASY48
2SA1700	Si-P	=2SA1699: 10W	30j	Say	2SA1198, 2SA1233, 2SA1496
2SA1701	Si-P	S, 15V, 1,5A, 0,9W, 300MHz	9c	Say	2SA968, 2SA1258, 2SA1703
2SA1702	Si-P	S, 25V, 5A, 1W, 320MHz, 40/210ns	8c	Say	2SA1431, 2SB1288, 2SB1305..07, 2SB1319
2SA1703	Si-P	NF, Io-sat, 30V, 1,5A, 1W, 180MHz	8c	Say	2SB926..927, 2SB892, 2SB1229
2SA1704	Si-P	NF, S, Io-sat, 30V, 2,5A, 1W, 150MHz	8c	Say	2SB892, 2SB985, 2SB1433..34
2SA1705	Si-P	NF, S, Io-sat, 80V, 1A, 0,9W, 150MHz	9c	Say	2SA1708, 2SB1116, 2SB1437
2SA1708	Si-P	NF, S, Io-sat, 60V, 2A, 1W, 150MHz	9c	Say	2SA1315, 2SB892, 2SB1229
2SA1707	Si-P	NF, S, Io-sat, 60V, 3A, 1W, 150MHz	9c	Say	2SB985
2SA1708	Si-P	NF, S, Io-sat, 120V, 1A, 1W, 120MHz	9c	Say	2SB1456
2SA1709	Si-P	NF, S, Io-sat, 120V, 12A, 1W, 120MHz	9c	Say	—
2SA171	Ge-P	HF/S, 20V, Ueb=10V, 0,05A, 0,125W, 8MHz	2a	Nec	ASY26..27, ASY46
2SA1710	Si-P	Vid, hi-def, 300/300V, 0,1A, 1W, 70MHz	9c	Say	2SA1371
2SA1711	Si-P	S, 20V, 0,03A, 0,2W, 15/110ns	41c	Tos	2N4313, 2N5056..57
2SA1712	Si-P	=2SA1711: SMD	35a	Tos	BSR12, 2SA1764
2SA1714	Si-P-Darl	S-L, 100/100V, 3A, 12W, B>2000	14h	Nec	(BD680, BD682, 2N6036)
2SA1715	Si-P-Darl+Di	S-L, 100V, 5A, 25W, 180MHz, B>2000	15c	Nec	2SB1339
2SA1718	Si-P-Darl+Di	S-L, 100V, 6A, 30W, 100MHz, B>4000	15c	Nec	2SB1343
2SA1717	Si-P-Darl+Di	S-L, 100V, 10A, 40W, 100MHz, B>4000	15c	Nec	—
2SA1718	Si-P-Darl	=2SA1715: Iso, 20W	17c	Nec	2SB1098, 2SB1430
2SA1719	Si-P-Darl	=2SA1716: Iso, 25W	17c	Nec	2SB1099, 2SB1431
2SA172	Ge-P	=2SA171: 0,2A, 0,175W	2a°	Nec	ASY26..27, ASY46
2SA1720	Si-P-Darl	=2SA1717: Iso, 25W	17c	Nec	2SB1432
2SA1721	Si-P	SMD, Nix, Video, 300V, 0,1A, 55MHz	35a	Tos	BFN27
2SA1722	Si-P+R	SMD, S, 50V, 0,1A, Rb=2,2kΩ, Rbe=10kΩ	35a(2mm)	Say	DTA123YU
2SA1723	Si-P	Vid, hi-def, 30/20V, 0,3A, 1500MHz	14h	Say	—
2SA1724	Si-P	SMD, Vid, hi-def, 30V, 0,3A, 1500MHz	39b	Say	—
2SA1725	Si-P	=2SA1725: Iso, 30W	17c	Sak	2SA1442, 2SA1470, 2SB1097, 2SB1290
2SA1726	Si-P	NF-L, 80V, 6A, 50W, 20MHz	17j	Sak	BD244B..F, BD544B..C, BD800, BD810++
2SA1727(F5)	Si-P	S, 400/400V, 0,5A, 10W, 12MHz	30c	Rhm	2SA1400
2SA1728	Si-P	SMD, S, 50V, 0,5A, 350MHz, 60/170ns	35a	Say	BSR15..16, 2SA1338
2SA1729	Si-P	SMD, S, 50V, 1,5A, 50/150ns	39b	Say	—
2SA173	Ge-P	HF/S, 20V, Ueb=10V, 0,05A, 0,125W, 4MHz	2a	Nec	ASY26..27, ASY46
2SA1730	Si-P	SMD, S, 50V, 3A, 300MHz, 50/150ns	39b	Say	—
2SA1731	Si-P	S-L, 50V, 5A, 15W, 300MHz, 50/150ns	30c	Say	—
2SA1732	Si-P	S-L, 50V, 6A, 15W, 250MHz, 50/150ns	30c	Say	—
2SA1733K	Si-P	SMD, HF, 30V, 0,03A, >200MHz	35a	Rhm	BC856..860, BF550, 2SA1256,++
2SA1734	Si-P	SMD, S, Io-sat, 40V, 1,2A, 100/300ns	39b	Tos	2SA1681, 2SB1123

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2SA1735	Si-P	SMD, S, Io-sat, 60V, 1A, 100/350ns	39b	Tos	2SA1661, 2SB1122..1123
2SA1736	Si-P	SMD, S, Io-sat, 60V, 3A, 100/300ns	39b	Tos	2SB1124
2SA1737	Si-P	=2SA1467: SMD	39b	Mat	—
2SA1738	Si-P	SMD, S, 15V, 0,05A, 1500MHz, 12/20ns	35a	Mat	BSR 12, 2SA1764
2SA1739	Si-P	=2SA1738:	35a(2mm)	Mat	2SA1610, 2SA1763
2SA174	Ge-P	=2SA173: 0,175W	2a°	Nec	ASY 26..27, ASY 48
2SA1740	Si-P	=2SA1699. SMD	39b	Say	2SA1612
2SA1741	Si-P	=2SA1441:	17c	Nec	→2SA1441
2SA1742	Si-P	=2SA1442:	17c	Nec	→2SA1442
2SA1743	Si-P	=2SA1443:	17c	Nec	→2SA1443
2SA1744	Si-P	=2SA1444:	17c	Nec	→2SA1444
2SA1745	Si-P	SMD, Io-sat, 20V, 0,5A, 400MHz	35a(2mm)	Say	—
2SA1748	Si-P	NF/S-L, Io-sat, 70V, 12A, 60W, 25MHz	18c	Sak	2SB1508..1509
2SA1747	Si-P	SMD, Uni, 50V, 0,05A, 250MHz	35a	Mat	BC856..657, BF550, 2SA1256, ++
2SA1748	Si-P	=2SA1747:	35a(2mm)	Mat	BC656W..857W, 2SA1603, 2SA1611
2SA1749	Si-P	Vid-E, hi-det, 200V, 0,3A, 10W, 400MHz	14b	Say	2SA1777
2SA175	Ge-P	RF/IF AMP, 15V, 50mA, 250MHz	2a	Tos	AF 124..126, AF 200, 2SA216..227
2SA1750	Si-P	Vid-E, hi-det, 140V, 0,5A, 10W, 500MHz	14b	Say	—
2SA1751	Si-P	=2SA1749: 20W	17j	Say	—
2SA1752	Si-P	=2SA1750: 20W	17j	Say	—
2SA1753	Si-P	=2SA1745:	35a(3mm)	Say	2SA1298, 2SA1621
2SA1755	Si-P	S, 100V, 0,7A, 0,9W, >100MHz, <60/400ns	7c(9mm)	Hit	2SA965, 2SA1013, 2SA1275
2SA1757	Si-P	NF/S-L, Io-sat, 100V, 5A, 25W, 80MHz	17c	Rhm	2SA1388, 2SA1441, 2SA1741
2SA1758	Si-P	NF/S-L, Io-sat, 100V, 12A, 30W, 80MHz	17c	Rhm	2SA1444, 2SA1744
2SA1759	Si-P	=2SA1760: SMD	39b	Rhm	2SA1740
2SA176	Ge-P	RF/IF AMP, 15V, 50mA, 250MHz	2a	Tos	AF 124..126, AF 200, 2SA218..227
2SA1760	Si-P	S, 400/400V, 0,1A, 0,9W, 12MHz	7c(9mm)	Rhm	2SA1372, 2SA1584, 2SB1363
2SA1761	Si-P	NF/S, 60V, 3A, 0,9W, 100MHz	7c(9mm)	Tos	2SA1707, 2SB985, 2SB1066
2SA1762	Si-P	=2SA777:	9c	Mat	→2SA777
2SA1763	Si-P	=2SA1764:	35a(2mm)	Say	—
2SA1764	Si-P	SMD, SS, 15V, 0,2A, 1GHz, 11/21ns	35a	Say	—
2SA1765	Si-P	S, 15V, 0,2A, 0,3W, 1GHz, <25/60ns	40c	Say	—
2SA1766	Si-P	SMD, hi-Ueb, hi-beta, Io-sat, 30V, 0,3A	39b	Say	—
2SA1767	Si-P	Uni, Vid, 300V, 0,07A, 0,75W, >50MHz	7c	Mat	BF 421(A), BF 437, BF 466, 2SA1371, ++
2SA1766	Si-P	S, 180/160V, 0,7A, 1W, 60/960ns	9c	Say	2SA1319, 2SA1770
2SA1769	Si-P	=2SA1768: 10W	14b	Rhm	2SA1507, (2SA1248..49)
2SA1770	Si-P	S, 160/160V, 1,5A, 1W, 40/740ns	9c	Say	(2SB1212)
2SA1771	Si-P	NF/S-L, hi-Ueb, 60V, 12A, 30W, 50MHz	17c	Tos	—
2SA1772	Si-P	S-L, 400/400V, 1A, 15W, 50MHz	30j	Say	2SA1379, 2SA1413, 2SA1807
2SA1773	Si-P	S-L, 400/400V, 2A, 15W, 40MHz	30j	Say	2SA1412
2SA1774	Si-P	=2SA1037:	35a(1,6mm)	Rhm	2SB1462
2SA1775	Si-P	S-L, 400/400V, 0,5A, 10W, 12MHz	14h	Rhm	2SA1156
2SA1776	Si-P	=2SA1775:	9c	Rhm	2SA1625, 2SB1074, 2SB1466
2SA1777	Si-P	Vid-E, hi-def, 250V, 0,3A, 10W, 400MHz	14b	Say	—
2SA1776	Si-P	SMD, VHF-O/V, 15V, 50mA, 600MHz	35	Say	BF 569, BF 579, BF 767
2SA1779	Si-P	S, 50V, 0,1A, 0,4W, >200MHz	7c	Hit	BC 556..557, 2N2906..07, 2SA1015, ++
2SA176	Ge-P	HF, 18V, 5mA	4g	Tos	AF 124..126, AF 200, 2SA218..227
2SA1760	Si-P	=2SA1775:	7c(9mm)	Rhm	2SA1625, 2SB1074, 2SB1468
2SA1761	Si-P	=2SA1762: SMD	35a	6ay	BC856, BCW89, 2SA1311
2SA1782	Si-P	Uni, 55V, 0,15A, 0,3W, 180MHz	40c	Say	BC 212, BC 256, BC 556, 2SA1265(A), ++
2SA1783	Si-P	=2SA1782: 0,5W	7c	Say	BC 212, BC 256, BC 556, 2SA1265(A), ++
2SA1764	Si-P	=2SA1699 1W	9c	Say	→2SA1699
2SA1765	Si-P	S, Tr, 400/400V, 1A, 1W, 50MHz	9c	Say	2SA1626
2SA1766	Si-P	S, Tr, 400/400V, 2A, 1W, 40MHz	9c	Say	2SA1626
2SA1787	Si-P	Vid, hi-det, 200/200V, 0,1A, 1W, 150MHz	9c	Say	2SA1370..71
2SA1788	Si-P	NF/S-L, -/120V, 8A, 60W	16c	Rhm	2SA1672, 2SA1605, 2SA1909
2SA1769	Si-P	NF/S-L, -/60V, 12A, 80W	16c	Rhm	2SA1909
2SA1790	Si-P	=2SA1022:	35a(1,6mm)	Mat	2SA1791
2SA1791	Si-P	=2SA1747:	35a(1,6mm)	Mat	—
2SA1792	Si-P	S-L, Io-sat, 50V, 10A, 15W, 45MHz	≈30c	Tos	—
2SA1793	Si-P	Io-sat, 60V, 5A, 15W, 60MHz, 100/1100ns	≈30c	Tos	(2SA1244, 2SA1795, 2SB1203)
2SA1794	Si-P	Io-sat, 100V, 5A, 15W, 60MHz, 200/1100ns	≈30c	Tos	(2SA1648)
2SA1795	Si-P	S-L, Io-sat, 60V, 5A, 10W, <300/2000ns	30j	Shi	2SA1244, 2SA1385, 2SA1401, 2SB1203
2SA1796	Si-P	S-L, Io-sat, 60V, 7A, 10W, <300/2000ns	30j	Shi	2SB1204
2SA1797	Si-P	SMD, NF, Io-sat, 50/50V, 2A	39b	Rhm	2SA1681, 2SA1738, 2SB1123..24
2SA1798	Si-P	S-L, Io-sat, 25V, 8A, 10W, 200MHz	14b	Say	—

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2SA1799	Si-P	Vid-E, hi-def, 180V, 0,3A, 20W, 400MHz	17j	Tos	S3746
2SA17H	Ge-P	=2SA17: 16V, Ueb=12V	2a		—
2SA18	Ge-P	HF/S, 21V, Ueb=0,5V, 15mA, 19MHz	2a	Hit	AF124..127, AF200, 2SA100, 2SA102
2SA180	Ge-P	HF/ZF, 15V, Ueb=15V, 10mA, 10MHz	2a	Say	(AF124..127, AF200, 2SA202)
2SA1600	Si-P	Vid-E, hi-def, 250V, 0,15A, 10W, 240MHz	17c	Tos	S3751
2SA1801	Si-P	=2SA1799: 6W	14b	Tos	2SA1749
2SA1802	Si-P	S-L, lo-sat, 30V, 3A, 10W, 160MHz	30j	Tos	2SB962, 2SB1202
2SA1803	Si-P	HiFi-NF-E, 80V, 6A, 55W, 30MHz	18c	Tos	2SA1670, 2SA1907, (BD246A..F)
2SA1804	Si-P	HiFi-NF-E, 120V, 8A, 70W, 30MHz	18c	Tos	2SA1671, 2SA1908, (BD246C..F)
2SA1805	Si-P	HiFi-NF-E, 140V, 10A, 60W, 30MHz	18c	Tos	2SA1672, 2SA1909, (BD246D..F)
2SA1806	Si-P	=2SA1738:	35a(1,6mm)	Mat	—
2SA1807(F5)	Si-P	S-L, 600/600V, 1A, 10W, 200/2200ns	30c	Rhm	2SA1379, 2SA1413
2SA1606	Si-P	=2SA1733K:	35a(2mm)	Rhm	BC856W..860W, 2SB1218
2SA1809	Si-P	S, 400/400V, 0,5A, 1,2W, 600/3700ns	76b	Rhm	2SA1400, 2SA1727
2SA161	Ge-P	HF/ZF, 15V, Ueb=15V, 10mA, 5MHz	2a	Say	(AF124..127, AF200, 2SA201..203)
2SA1610	Si-P	Vid-E, 200/200V, 0,2A, 10W, 300MHz	14h	Hit	2SA1407
2SA1611	Si-P	NF/S, 35V, 0,5A, 0,6W, 200MHz	7c(9mm)	Tos	2SA1533, 2SA1683, 2SB967, 2SB1297
2SA1812	Si-P	=2SA1775: SMD	39b	Rhm	—
2SA1613	Si-P	=2SA1614:	35a(2mm)	Say	—
2SA1614	Si-P	SMD, Uni, 30V, 0,15A, 210MHz, B>500	35	Say	—
2SA1615	Si-P	SMD, HF, 15V, 50mA, 750MHz	35a	Say	BF569, BF579, BF767
2SA1616	Si-P	Uni, ra, 150V, 0,05A, 0,3W, 200MHz	40c	Mat	2SA1016K, 2SA1123..1124, 2SA1482
2SA1818	Si-P	Uni, -/32V, 1A, 0,9W	7c(9mm)	Rhm	2SA1315, 2SB764, 2SB892, 2SB1041, ++
2SA1819	Si-P	Uni, -/150V, 0,05A, 0,6W	7c(9mm)	Rhm	BF436, BF423A, 2SA1281, 2SA1370
2SA182	Ge-P	HF/ZF, 15V, Ueb=15V, 10mA, 5MHz	2a	Say	(AF124..127, AF200, 2SA201..203)
2SA1820	Si-P	NF-Tr/E, -/50V, 2A, 0,9W	7c(9mm)	Rhm	2SA1315, 2SB892, 2SB1459
2SA1821	Si-P	SMD, HF, -/20V, 50mA, 400MHz	35a(1,6mm)	Rhm	—
2SA1822	Si-P	S-L, 400/400V, 1A, 25W, <1/6ns	17c	Tos	2SA1397
2SA1623	Si-P	S-L, 25V, 8A, 200MHz, 30/215ns	≈12b	Say	—
2SA1624	Si-P	S-L, 80V, 5A, 130MHz, 50/470ns	≈12b	Say	—
2SA1625	Si-P	S-L, 80V, 8A, 130MHz, 50/470ns	≈12b	Say	—
2SA1826	Si-P	S-L, 120V, 3A, 130MHz, 100/850ns	≈12b	Say	—
2SA1827	Si-P	S-L, 120V, 4A, 130MHz, 100/650ns	≈12b	Say	—
2SA1626	Si-P	=2SA1352: 1,3W, 150MHz	≈12b	Say	(2SA1380..81)
2SA1629	Si-P	=2SA1353: 1,5W, 150MHz	≈12b	Say	(2SA1381)
2SA163	Ge-P	HF/ZF, 15V, Ueb=15V, 10mA, 16MHz	2a	Say	(AF124..127, AF200, 2SA202)
2SA1830	Si-P	S, 400/400V, 2A, 1,5W, 40MHz	≈12b	Say	—
2SA1831	Si-P	S-L, 600/800V, 20mA, 25W, 10MHz	17j	Say	—
2SA1832	Si-P	SMD, NF, ra, 50V, 0,15A, >60MHz	35a(1,6mm)	Tos	2SB1482
2SA163	Si-P-Darl+Di	S-L, 100V, 8A, 25W, 100MHz, B>4000	17c	Nec	2SB1263..64
2SA1634(F5)	Si-P	NF-L, lo-sat, 30V, 10A, 10W, 150MHz	30c	Rhm	2SA1615
2SA1835S	Si-P	S, -/40V, 0,2A, 0,25W	41c	Rhm	BSW24, 2N2906..07(A), 2SA1339, ++
2SA1638	Si-P	SMD, NF, 60V, 0,1A, 0,2W, >50MHz	35a(1,6mm)	Nec	2SB1482
2SA1637	Si-P	NF-L, 230/230V, 1A, 20W, 70MHz	17c	Tos	—
2SA1636	Si-P	=2SA1639:	35a(2mm)	Say	—
2SA1839	Si-P	SMD, Muting, 15V, 0,1A, 600MHz, Ron=3Ω	35a	Say	—
2SA184	Ge-P	HF/ZF, 15V, Ueb=15V, 10mA, 3MHz	2a	Say	(AF124..127, AF200, 2SA201)
2SA1840	Si-P-Darl+Di	S-P, 100/100V, 5A, 20W, B>2000	78c	Nec	(→2SA1715)
2SA1841	Si-P-Darl+Di	S-L, 100/100V, 6A, 20W, B>4000	78c	Nec	(→2SA1716)
2SA1642	Si-P-Darl+Di	S-L, 100/100V, 10A, 20W, B>4000	78c	Nec	(→2SA1717)
2SA1643	Si-P	lo-sat, 100/60V, 5A, 1,6W, 60MHz	78c	Nec	(→2SA1441)
2SA1644	Si-P	lo-sat, 100/60V, 7A, 1,6W, 40MHz	78c	Nec	(→2SA1442)
2SA1645	Si-P	lo-sat, 150/100V, 5A, 1,6W, 150MHz	78c	Nec	(→2SA1644)
2SA1846	Si-P	lo-sat, 150/100V, 7A, 1,8W, 150MHz	78c	Nec	(→2SA1645)
2SA1847	Si-P	lo-sat, 150/100V, 10A, 1,8W, 150MHz	78c	Nec	(→2SA1846)
2SA1648	Si-P	=2SA1536: 1,3W	≈12b	Say	(→2SA1538)
2SA1649	Si-P	=2SA1537: 1,3W	≈12b	Say	(→2SA1537)
2SA1650	Si-P	=2SA1536: 1,3W	≈12b	Say	(→2SA1538)
2SA1651	Si-P	=2SA1539: 1,3W	≈12b	Say	(→2SA1539)
2SA1652	Si-P	=2SA1540: 1,3W	≈12b	Say	(→2SA1540)
2SA1853	Si-P	=2SA1541: 1,3W	≈12b	Say	(→2SA1541)
2SA1854	Si-P	S, 25V, 5A, 1,5W, 320MHz, 40/210ns	≈12b	Say	—
2SA1655	Si-P	S, 80V, 4A, 1,5W, 150MHz, 70/480ns	≈12b	Say	—
2SA1856	Si-P	S-L, 400/400V, 4A, 30W, <700/2000ns	17c	Tos	2SA1501
2SA1657	Si-P	=2SA1615:	35a(2mm)	Say	—
2SA1656	Si-P	=2SA1767: 1W	7c(9mm)	Mat	2SA1371..72, 2SA1584, 2SA1760, 2SB1363

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2SA1859	Si-P	TV, NF-L, 150/150V, 2A, 20W, 60MHz	17c	Sak	2SA1306, 2SA1332, 2SA1606, 2SB1186A
2SA1859A	Si-P	=2SA1859: 180/180V	17c		2SA1306A. B, 2SA1606
2SA1860	Si-P	NF/S-L, 150/150V, 14A, 80W, 50MHz	18c	Sak	2SA1873
2SA1861	Si-P	=2SA1862: 1,2W	78b	Rhm	(→2SA1862)
2SA1862(F5)	Si-P	S, 400/400V, 2A, 10W, 18MHz, 200/2200ns	30c	Rhm	2SA1412, 2SA1773
2SA1863	Si-P	=2SA1815:	35a(1,6mm)	Say	—
2SA1864	Si-P	SMD, Muting, 15V, 0,1A, 600MHz, Ron=5Ω	35a(1,6mm)	Say	—
2SA1865	Si-P	SMD, Muting, 15V, 0,1A, 600MHz, Ron=6Ω	35a(1,6mm)	Say	—
2SA1866	Si-P	SMD, Muting, 15V, 0,05A, 600MHz, Ron=10Ω	35a(1,6mm)	Say	—
2SA1868	Si-P	S, 400/400V, 0,6A, 10W, 180MHz	30j	Mat	2SA1727, 2SA1400
2SA1869	Si-P	L, 50V, 3A, 10W, 100MHz	17c	Tos	2SA1307, 2SA1440, 2SA1469, 2SB1185
2SA1870	Si-P	S-L, Io-sat, 100V, 12A, 35W, 80MHz	30j	Rhm	—
2SA1871	Si-P	SMD, S, 600/600V, 1A, 30MHz, <0,5/5,5µs	39b	Nec	—
2SA1873	Si-P	=2SA1818:	45(2mm)	Tos	—
2SA1875	Si-P	=2SA1749: 12W	30j	Say	(→2SA1749)
2SA1876	Si-P	S-L, Io-sat, 80V, 3A, 10W, 50MHz	30j	Shi	2SB1215..1216
2SA1877	Si-P	S-L, Io-sat, 80V, 5A, 10W, 50MHz	30j	Shi	2SA1648
2SA1878	Si-P	S-L, Io-sat, 80V, 5A, 25W, 50MHz	15c	Shi	2SA1469, 2SA1388, 2SA1741
2SA1879	Si-P	S-L, Io-sat, 80V, 7A, 25W, 50MHz	15c	Shi	2SA1470, 2SA1742
2SA188	Ge-P	HF/ZF, 12V, 15mA, 10MHz	2a	Fui	AF 124..127, AF 200, 2SA201..202
2SA1880	Si-P	S-L, Io-sat, 80V, 10A, 25W, 50MHz	15c	Shi	2SA1471, 2SA1743
2SA1881	Si-P	SMD, 15V, 1A, 300MHz	35	Say	—
2SA1882	Si-P	SMD, 15V, 1,5A, 300MHz	39b	Say	2SA1314, 2SA1363, 2SA1389, 2SA1863,++
2SA1883	Si-P	SMD, SS, 15V, 0,2A, 1000MHz, 11/19ns	35a(1,6mm)	Say	—
2SA1884	Si-P	S, -/400V, 0,5A, 0,9W	7c(9mm)	Rhm	2SA1625, 2SB1074, 2SB1488
2SA1885	Si-P	SMD, HF, S, -/10V, 0,1A, 650MHz	35a(2mm)	Rhm	—
2SA1886	Si-P	=2SA1885:	35a(1,6mm)	Rhm	—
2SA1887	Si-P	NF/S-L, Io-sat, 80V, 10A, 45MHz	17c	Tos	2SA1443, 2SA1471, 2SA1743
2SA1888	Si-P	SMD, FM-ZF, 30V, 30mA, 300MHz	35d	Mat	BF 550, 2SA1256
2SA1889	Si-P	=2SA1810: Iso, 8W	14b	Hit	2SA1749, 2SA1777
2SA189	Ge-P	HF/ZF, 12V, 15mA, 6MHz	2a	Fui	AF 124..127, AF 200, 2SA201..203
2SA1890	Si-P	SMD, Io-sat, 80V, 1A, 120MHz	39b	Mat	2SB1115A, 2SB1520
2SA1891	Si-P	Uni, Io-sat, 80V, 2A, 1,3W, 100MHz	12b	Tos	(2SB1142)
2SA1892	Si-P	Uni, 50V, 3A, 1,3W, 100MHz	12b	Tos	—
2SA1893	Si-P	35V, 5A, 1,3W, 170MHz	12b	Tos	(2SA1357, 2SB1436)
2SA1896	Si-P	SMD, 25V, 2,5A, 400MHz	39b	Say	2SA1736, 2SB1124, 2SB1518
2SA1897	Si-P	Io-sat, 30V, 5A, 1W, 180MHz, 400/360ns	9b	Nec	(2SA1431, 2SB1050, 2SB1319, 2SB1398)
2SA1898	Si-P	SMD, S, 15V, 3A, 30/120ns	39b	Say	2SB1301, 2SB1518, 2SB1628
2SA1899	Si-P	Uni, 120V, 0,6A, 1W, 120MHz	9c	Tos	2SA985, 2SA1013, 2SA1319, 2SA1786,++
2SA18H	Ge-P	=2SA18: Ueb=12V	2a		—
2SA19	Ge-P	AM-ZF, 12V, 2mA, 50MHz	2a	Nec	AF 124..126, AF 200, 2SA104
2SA190	Ge-P	AM-V/M, 20V, 15mA, 40MHz	4g	Oki	AF 124..126, AF 200, 2SA218..227
2SA1900	Si-P	SMD, Io-sat, 80V, 1A, 150MHz	39b	Rhm	2SA1384, 2SB1115(A), 2SB1122..23
2SA1902	Si-P	Uni, -/80V, 0,7A, 0,9W	7c(9mm)	Rhm	2SA1013, 2SA1275, 2SB647, 2SB1212
2SA1903	Si-P	Io-sat, -/20V, 3A, 0,9W	7c(9mm)	Rhm	2SB985, 2SB1505
2SA1905	Si-P	Uni, Io-sat, 80V, 5A, 1,3W, 80MHz	12b	Tos	(2SB1267)
2SA1907	Si-P	NF/S-L, 80V, 6A, 60W, 20MHz	18c	Sak	2SA1670, 2SA1803, (BD 246A..F)
2SA1908	Si-P	NF/S-L, 120V, 6A, 75W, 20MHz	18c	Sak	2SA1671, 2SA1804, (BD 246C..F)
2SA1909	Si-P	NF/S-L, 140V, 10A, 80W, 20MHz	18c	Sak	2SA1672, 2SA1805, (BD246D..F)
2SA191	Ge-P	AM-M/O, 20V, 15mA, 20MHz	4g	Oki	AF 124..126, AF 200, 2SA218..227
2SA192	Ge-P	AM-ZF, 20V, 15mA, 13MHz	4g	Oki	AF 124..127, AF 200, 2SA218..227
2SA192	Si-P	S-/600V, 0,1A, 1W	9c	Rhm	—
2SA1923	Si-P	S-L, 400/400V, 0,5A, 10W, 200/2200ns	30j	Tos	2SA1772
2SA1924	Si-P	=2SA1924:	14b	Tos	(2SA1156, 2SA1775)
2SA1925	Si-P	=2SA1924: 1,5W(Ta=25°)	12b	Tos	(2SA1156, 2SA1775)
2SA1926	Si-P	Io-sat, 80V, 3A, 1W, 80MHz	9c	Tos	—
2SA193	Ge-P	AM-V/M, 15V, Ueb=12V, 15mA, 13MHz	2a	Oki	(AF 124..126, AF 200, 2SA202)
2SA1930	Si-P	TV, L, 180/180V, 2A, 20W, 200MHz	17c	Tos	2SA1306A, 2SA1606, 2SA1859A
2SA1932	Si-P	Uni, 230/230V, 1A, 1,8W, 70MHz	15c	Tos	2SA1837
2SA1933	Si-P	Uni, Io-sat, 80V, 5A, 1,8W, 80MHz	15c	Tos	2SA1388, 2SA1489..70, 2SA1441
2SA1934	Si-P	Uni, Io-sat, 100V, 5A, 1,8W, 60MHz	15c	Tos	2SA1388, 2SA1441, 2SA1741
2SA1935	Si-P	SMD, S, 15V, 1,5A, 300MHz, 30/120ns	39b	Say	2SA1314, 2SA1383, 2SA1389, 2SA1663,++
2SA1936	Si-P	SMD, S, 15V, 5A, 300MHz, 30/120ns	39b	Say	2SB1302, 2SB1308, 2SB1388
2SA1937	Si-P	S-L, 600/600V, 0,5A, 10W, 35MHz	30j	Tos	2SA1379, 2SA1413, 2SA1807
2SA1939	Si-P	NF-HiR-E, 80/80V, 6A, 80W, 30MHz	18j	Tos	BD 246C, BDV 94, 2SA1693, 2SB775,++
2SA194	Ge-P	AM-ZF, 15V, Ueb=12V, 15mA, 7MHz	2a	Oki	(AF 124..127, AF 200, 2SA201)

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2SA1940	Si-P	NF-HiFi-E, 120/120V, 8A, 80W, 30MHz	18j	Tos	BD246C, BD546D, 2SA1694, 2SB688, ++
2SA1941	Si-P	NF-HiFi-E, 140/140V, 10A, 100W, 30MHz	18j	Tos	BD246D, 2SA1146, 2SA1186, 2SA1491, ++
2SA1942	Si-P	NF-HiFi-E, 180/180V, 12A, 120W, 30MHz	77j	Tos	2SA1302, 2SB1317, 2SB1429
2SA1943	Si-P	NF-HiFi-E, 230/230V, 15A, 150W, 25MHz	77j	Tos	2SA1553
2SA1944	Si-P	SMD, Uni, 50V, 1A, 90MHz, B=400..1200	39b	Tos	2SA1681, 2SB1115, 2SB1122..1123, ++
2SA1945	Si-P	SMD, Uni, 55V, 0,4A, 150MHz	39b	Tos	2SA1202, 2SA1662, 2SB1122..1123, ++
2SA1946	Si-P	SMD, Uni, 25V, 0,7A, 180MHz	39b	Tos	BCX51..53, 2SA1364, 2SB1734, 2SB804, ++
2SA1947	Si-P	SMD, Uni, 30V, 1A, 100MHz	39b	Tos	BCX51..53, 2SA1681, 2SB1122..1123, ++
2SA1948	Si-P	SMD, Uni, 120V, 0,1A, 200MHz	39b	Tos	2SA1173, 2SA1200, 2SB1045..1047
2SA1949	Si-P	S-L, 490/490V, 0,5A, 10W, 70MHz	30j	Mat	2SA1379, 2SA1413, 2SA1807
2SA195	Ge-P	AM-ZF, 15V, Ueb=12V, 15mA, 4MHz	2a	Oki	(AF124..127, AF200, 2SA203)
2SA1950	Si-P	S-L, 500/500V, 1A, 10W	30j	Mat	2SA1379, 2SA1413, 2SA1807
2SA1951	Si-P	S-L, 500/500V, 2A, 100W	30j	Mat	—
2SA1956	Si-P	Vid E, 150/150V, 0,2A, 8W, 500MHz	14b	Hit	2SA1749, 2SA1777
2SA196	Ge-P	AM-ZF, 15V, Ueb=12V, 15mA, 2,5MHz	2a	Oki	(AF124..127, AF200, 2SA203)
2SA1960	Si-P	HF, Vid, 80/80V, 0,3A, 0,625W, 1,3GHz	7e	Hit	—
2SA1962	Si-P	=2SA1943: 130W	18j	Tos	2SA1294
2SA1963	Si-P	SMD, VHF/UHF, 12V, 50mA, 5GHz	35a	Say	BFT93
2SA1965	Si-P	SMD, Muting, 15V, 0,1A, Ron=1,2Ω	35a(1,6mm)	Say	—
2SA1966	Si-P	S-L, 500/500V, 0,1A, 10W, 30MHz	30j	Mat	—
2SA1967	Si-P	CRT, S-L, 900/900V, 100mA, 6MHz	17j	Say	—
2SA1966(LS)	Si-P	=2SA1967: Iso	17c	Say	—
2SA1969	Si-P	SMD, 10/10V, 0,4A, 1,7GHz	39b	Say	—
2SA197	Ge-P	AM-ZF, 15V, Ueb=15V, 10mA	2a	Oki	(AF124..127, AF200, 2SA202)
2SA1971	Si-P	SMD, S, 400/400V, 0,5A, 35MHz	39b	Tos	—
2SA1974	Si-P	Uni, 40V, 0,5A, 0,5W, 200MHz	7		BC327, BC636, 2SB734, 2SB909..910, ++
2SA1975	Si-P	Uni, 50V, 0,15A, 0,4W, 80MHz	7		BC212, BC307, BC556..557, 2SB725, ++
2SA1976	Si-P	Uni, 35V, 0,8A, 0,625W, 130MHz	7		BC327, BC636, 2SB734, 2SB909..910, ++
2SA198	Ge-P	AM-ZF, 15V, 15mA	2a	Oki	AF124..127, AF200, 2SA201..203
2SA199	Ge-P	AM-VM, 15V, 5mA	2a	Oki	AF124..126, AF200, 2SA201..203
2SA20	Ge-P	AM-ZF, 12V, 2mA, 55MHz	2a	Nec	AF124..126, AF200, 2SA104
2SA200	Ge-P	AM-VM, 15V, 5mA	2a	Oki	AF124..126, AF200, 2SA201..203
2SA201	Ge-P	AM-VM, 15V, 15mA, 8MHz	2a	Say	AF124..126, AF200, 2SA101..104
2SA202	Ge-P	AM-ZF, 15V, 15mA, 12MHz	2a	Say	AF124..127, AF200, 2SA101..104
2SA203	Ge-P	AM-ZF, 15V, 15mA, 5MHz	2a	Say	AF124..127, AF200, 2SA101..104
2SA204	Ge-P	HF/S, 30V, Ueb=20V, 0,2A, 0,15W, 6MHz	2a	Nec	ASY26..27, ASY48
2SA205	Ge-P	HF/S, 30V, Ueb=20V, 0,2A, 0,2W, 5MHz	2a	Nec	ASY26..37, ASY48
2SA206	Ge-P	HF/S, 30V, Ueb=20V, 0,2A, 0,2W, 7MHz	2a	Nec	ASY26..27, ASY48
2SA207	Ge-P	HF/S, 30V, Ueb=20V, 0,2A, 0,2W, 12MHz	2a	Nec	ASY26..27, ASY48
2SA206	Ge-P	S, 20V, Ueb=12V, 0,4A, 0,12W, >3MHz	2a	Hit	ASY76..77
2SA209	Ge-P	S, 20V, Ueb=12V, 0,4A, 0,12W, >5MHz	2a	Hit	ASY76..77
2SA21	Ge-P	AM-ZF, 12V, 2mA, 55MHz	2a	Nec	AF124..126, AF200, 2SA104
2SA210	Ge-P	S, 20V, Ueb=12V, 0,4A, 0,12W, >10MHz	2a	Hit	ASY76..77
2SA211(H)	Ge-P	S, 18V, Ueb=10V, 0,1A, 0,12W, >4MHz	2a	Hit	ASY26..27, ASY48
2SA212(H)	Ge-P	=2SA211: 25V, Ueb=12V	2a	Hit	ASY26..27, ASY48
2SA213	Ge-P	FM-VM, 15V, 2mA, 140MHz	2a	Nec	AF124..125, AF106, AF306, 2SA342
2SA214	Ge-P	FM-O/ZF, 15V, 2mA, 140MHz	2a	Nec	AF124..126, AF106, AF306, 2SA342
2SA215	Ge-P	FM-ZF, 15V, 2mA, 120MHz	2a	Nec	AF124..126, AF106, AF306, 2SA340..342
2SA216	Ge-P	FM-ZF, 15V, 2mA, 120MHz	2a	Nec	AF124..126, AF106, AF306, 2SA340..342
2SA217(H)	Ge-P	HF/S, 25V, Ueb=12V, 0,1A, 0,12W, 14MHz	2a	Hit	ASY26..27, ASY48
2SA218	Ge-P	RF/IF AMP, 20V, 10mA, 0,08W, 400MHz	4g	Say	AF124..126, AF200, 2SA102..104
2SA219	Ge-P	FM-ZF, 20V, 15mA, 55MHz	2a	Say	AF124..126, AF200, 2SA103..104
2SA22	Ge-P	HF/ZF, 20V, 20mA, 12MHz	2a	Fui	AF124..127, AF200, 2SA201..202
2SA220	Ge-P	AM-V/M/O, 20V, 15mA, 60MHz	2a	Say	AF124..126, AF200, 2SA104
2SA221	Ge-P	AM-VM/O, 20V, 15mA, 55MHz	2a	Say	AF124..126, AF200, 2SA104
2SA222	Ge-P	AM-V/M/O, 20V, 15mA, 80MHz	2a	Say	AF124..126, AF200, 2SA104
2SA223	Ge-P	AM-O, 20V, 15mA, 65MHz	2a	Say	AF124..126, AF200, 2SA104
2SA224	Ge-P	RF/IF AMP, 20V, 10mA, 0,08W, 400MHz	4g	Say	AF124..126, AF200, 2SA104
2SA225	Ge-P	AM-V/M/O, 20V, 15mA, 55MHz	2a	Say	AF124..126, AF200, 2SA103..104
2SA226	Ge-P	RF/IF AMP, 20V, 10mA, 0,08W, 400MHz	4g	Say	AF124..126, AF200, 2SA104
2SA227	Ge-P	RF/IF AMP, 20V, 10mA, 0,08W, 400MHz	4g	Say	AF124..126, AF200, 2SA104
2SA228	Ge-P	RF/IF AMP, 20V, 10mA, 0,08W, 400MHz	4g		AF118, SFT162, 2SA358
2SA229	Ge-P	VHF/UHF, 20V, 5mA, 400MHz	5g	Tos	AF139, AF239(S)
2SA23	Ge-P	HF/ZF, 20V, 15mA, 8MHz	2a	Fui	AF124..127, AF200, 2SA201..203
2SA230	Ge-P	VHF/UHF, 20V, 5mA, 400MHz	5g	Tos	AF139, AF239(S)
2SA231	Ge-P	NF/HF/S, 40V, 0,4A, 3W(Tc=25°), 2,5MHz	2a	Hit	(AD162)

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2SA232	Ge-P	NF/HF/S, 30V, 0,4A, 3W(Tc=25°), 4MHz	2a	Hit	(AD162)
2SA233	Ge-P	RF/IF AMP, 20V, 10mA, 0,08W, 400MHz	4g	Hit	AF124..127, AF200, 2SA342
2SA234(H)	Ge-P	RF/IF AMP, 20V, 10mA, 0,08W, 400MHz	4g	Hit	AF124..127, AF200, 2SA342
2SA235(H)	Ge-P	RF/IF AMP, 20V, 10mA, 0,08W, 400MHz	4g	Hit	AF124..125, AF200, AF106, AF306
2SA236	Ge-P	RF/IF AMP, 15V, 50mA, 0,08W, 250MHz	2a	Tos	AF124..126, AF200, 2SA101..104
2SA237	Ge-P	RF/IF AMP, 15V, 50mA, 0,08W, 250MHz	2a	Tos	AF124..126, AF200, 2SA101..104
2SA238	Ge-P	VHF/UHF, 25V, 30mA, 700MHz	2a	Nec	(AF139, AF239(S))
2SA239	Ge-P	FM/VHF, 20V, 5mA, 200MHz	5g	Tos	AF106, AF109R, AF139, AF239(S)
2SA24	Ge-P	HF, 30V, 10mA, 100MHz	5g	Fui	AF124..126, AF200, AF239, 2SA104
2SA240	Ge-P	FM/VHF, 20V, 5mA, 200MHz	5g	Tos	AF106, AF109R, AF139, AF239(S)
2SA241	Ge-P	FM/VHF, 20V, 5mA, 200MHz	1g	Mat	AF106, AF109R, AF139, AF239(S)
2SA242	Ge-P	FM/VHF, 20V, 5mA, 250MHz	1g	Mat	AF106, AF109(R), AF139, AF239(S)
2SA243(A)	Ge-P	FM/VHF, 20V, 5mA, 300MHz	1g	Mat	AF109R, AF139, AF239(S)
2SA244(A)	Ge-P	FM/VHF, 25V, 30mA, 600MHz	2a	Nec	AF109R, AF139, AF239(S)
2SA245	Ge-P	FM/VHF, 25V, 30mA, 700MHz	2a	Nec	AF109(R), AF139, AF239(S)
2SA246(H)	Ge-P	RF/IF AMP, 15V, 50mA, 0,08W, 250MHz	2a	Hit	AF106, AF109R, AF139, AF239(S)
2SA247	Ge-P	RF/IF AMP, 15V, 50mA, 0,08W, 250MHz	2a	Hit	ASZ21, 2N2955..2957
2SA248	Ge-P	S, 10V, 0,3A, 0,1W, 40MHz, -/250ns	2a	Tos	ASZ21, 2N2955..2957
2SA249	Ge-P	HF, 100V, 10mA, 0,11W, 50MHz, β=60	2a	Mat	AF118, SFT162, 2SA358
2SA25	Ge-P	HF, 30V, 15mA, 100MHz	5g	Fui	AF124..126, AF200, AF239, 2SA104
2SA250	Ge-P	=2SA249: β=100	2a		AF118, SFT162, 2SA358
2SA251	Ge-P	S, 15V, Ueb=15V, 0,05A, 0,05W, 50MHz	2a	Fui	ASZ21, 2N2955..2957
2SA252	Ge-P	S, 15V, 0,05A, 0,05W, 80MHz	2a	Fui	ASZ21, 2N2955..2957
2SA253	Ge-P	VHF/UHF, 20V, 30mA, 450MHz	2a	Fui	AFY18, (AF139, AF239(S))
2SA254	Ge-P	AM-V/M/O, 12V, 10mA, 10MHz	37a	Fui	AF124..126, AF200, 2SA201..202
2SA255	Ge-P	AM-ZF, 12V, 10mA, 5MHz	37e	Fui	AF124..126, AF200, 2SA201..203
2SA256	Ge-P	AM-V/M/O, 20V, 10mA, 60MHz	37a	Fui	AF124..126, AF200, 2SA104
2SA257	Ge-P	AM-V/M/O, 20V, 10mA, 50MHz	37a	Fui	AF124..126, AF200, 2SA104
2SA258	Ge-P	AM-O, 20V, 10mA, 40MHz	37a	Fui	AF124..126, AF200, 2SA103..104
2SA259	Ge-P	AM-V/M/O, 20V, 10mA, 30MHz	37a	Fui	AF124..126, AF200, 2SA103..104
2SA26	Ge-P	HF, 20V, Ueb=15V, 50mA, 6MHz	2a	Nec	(AF121S, AF202(S), AFY18)
2SA260	Ge-P	FMA/HF, 20V, 10mA, 300MHz	5g	Sey	AF109R, AF139, AF239(S)
2SA261	Ge-P	FMA/HF, 20V, 10mA, 300MHz	5g	Say	AF109R, AF139, AF239(S)
2SA262	Ge-P	FMA/HF, 20V, 10mA, 450MHz	5g	Say	AF139, AF239(S)
2SA263	Ge-P	FMA/HF, 20V, 10mA, 500MHz	5g	Sey	AF139, AF239(S)
2SA264	Ge-P	FMA/HF, 20V, 10mA, 450MHz	5g	Say	AF139, AF239(S)
2SA265	Ge-P	FMA/HF, 20V, 10mA, 300MHz	5g	Say	AF109R, AF139, AF239(S)
2SA266	Ge-P	AM-V/M/O, 20V, 10mA, 60MHz	2a	Fui	AF124..126, AF200, 2SA104
2SA267	Ge-P	AM-V/M/O, 20V, 10mA, 50MHz	2a	Fui	AF124..126, AF200, 2SA104
2SA268	Ge-P	AM-O, 20V, 10mA, 40MHz	2a	Fui	AF124..126, AF200, 2SA103..104
2SA269	Ge-P	AM, 20V, 10mA, 30MHz	2a	Fui	AF124..126, AF200, 2SA102..104
2SA27	Ge-P	HF, 18V, 5mA, 50MHz	4g	Tos	AF124..126, AF200, AF239, 2SA104
2SA270	Ge-P	AM-VM, 9V, 10mA, 50MHz	2a	Fui	AF124..126, AF200, 2SA103..104
2SA271	Ge-P	AM-VM, 9V, 10mA, 30MHz	2e	Fui	AF124..126, AF200, 2SA103..104
2SA272	Ge-P	AM-ZF, 9V, 10mA, 20MHz	2e	Fui	AF124..127, AF200, 2SA102..104
2SA273	Ge-P	AM-V/M/O, 34V, 10mA, 40MHz	2a	Fui	AF124..126, AF200, 2SA103..104
2SA274	Ge-P	AM-ZF, 34V, 10mA, 30MHz	2a	Fui	AF124..127, AF200, 2SA102..104
2SA275	Ge-P	AM-V/M/O, 34V, 10mA, 45MHz	2a	Fui	AF124..126, AF200, 2SA103..104
2SA276	Ge-P	SS, 15, 0,03A, 0,075W, 210MHz, -/3,2ns	5g	Tos	ASZ21, 2N2955..2957
2SA277	Ge-P	S, 18V, 0,04A, 0,065W, >3,5MHz, -/450ns	2a	Tos	ASY26..27, ASY48
2SA278	Ge-P	S, 18V, 0,04A, 0,065W, >11MHz, -/400ns	2a	Tos	ASY26..27, ASY48
2SA279	Ge-P	AM/FM, 30V, 30mA, 150MHz	1g	Mat	AF124..126, AF200, AF106, AF109R
2SA28	Ge-P	HF, 18V, 5mA, >60MHz	4g	Tos	AF124..126, AF200, AF239, 2SA104
2SA280	Ge-P	AM/FM, 30V, 30mA, 70MHz	1g	Mat	AF124..126, AF200, AF106, AF109R
2SA281	Ge-P	AM/FM, 30V, 30mA, 100MHz	1g	Mat	AF124..126, AF200, AF106, AF109R
2SA282	Ge-P	S, 18V, Ueb=12V, 0,2A, 0,15W, 6MHz	2a	Tos	ASY26..27, ASY48
2SA283	Ge-P	S, 16V, Ueb=12V, 0,2A, 0,15W, 10MHz	2a	Tos	ASY26..27, ASY48
2SA284	Ge-P	S, 18V, Ueb=12V, 0,2A, 0,15W, 14MHz	2a	Tos	ASY26..27, ASY48
2SA285	Ge-P	RF/IF AMP, 20V, 10mA, 0,08W, 400MHz	4g	Nec	AF124..126, AF200, 2SA103..104
2SA286	Ge-P	RF/IF AMP, 20V, 10mA, 0,08W, 400MHz	4g	Nec	AF124..126, AF200, 2SA103..104
2SA287	Ge-P	RF/IF AMP, 20V, 10mA, 0,08W, 400MHz	4g	Nec	AF124..126, AF200, 2SA103..104
2SA288	Ge-P	FM/VHF, 20V, 10mA, 330MHz	1g	Hit	AF109R, AF139, AF239(S)
2SA289	Ge-P	FM/VHF, 20V, 10mA, 350MHz	1g	Hit	AF109R, AF139, AF239(S)
2SA29	Ge-P	RF/IF AMP, 15V, 50mA, 250MHz	2a	Tos	AF124..126, AF200, AF239, 2SA104
2SA290	Ge-P	FM/VHF, 20V, 10mA, 370MHz	1g	Hit	AF109R, AF139, AF239(S)
2SA291	Ge-P	FM/VHF, 20V, 50mA, 100MHz	2a	Fui	AF106, AF109R, AF139, AF239(S)

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2SA292	Ge-P	FM/VHF, 15V, 50mA, 200MHz	2a	Fui	AF106, AF109R, AF139, AF239(S)
2SA293	Ge-P	FM/VHF, 15V, 50mA, 300MHz	2a	Fui	AF109R, AF139, AF239(S)
2SA294	Ge-P	FM/VHF, 15V, 50mA, 400MHz	2a	Fui	AF109R, AF139, AF239(S)
2SA295	Ge-P	FM/VHF, 15V, 50mA	2a	Fui	AF109R, AF139, AF239(S)
2SA296	Ge-P	HF, 15V, 15mA, 5MHz	2a	old	AF124..127, AF200, 2SA101..104
2SA297	Ge-P	HF, 16V, 15mA, 10MHz	2a	old	AF124..127, AF200, 2SA101..104
2SA298	Ge-P	RF/IF AMP, 20V, 10mA, 400MHz	4g	old	AF124..127, AF200, 2SA101..104
2SA299	Ge-P	AM-ZF, 15V, 100mA	2a	Say	(AF124..127, AF200, 2SA102..104
2SA30	Ge-P	HF, 12V, 10mA, 10MHz	2a	Fui	AF124..127, AF200, 2SA201..202
2SA300	Ge-P	AM-ZF, 15V, 10mA	2a	Say	AF124..127, AF200, 2SA102..104
2SA301	Ge-P	HF/S, 30V, 30mA, 100MHz	1g	Mat	AF121(S), AF202(S)
2SA302	Ge-P	S, 20V, Ueb=15V, 0,1A, 0,063W, 6MHz	1a	Mat	ASY26..27, ASY48
2SA303	Ge-P	S, 20V, Ueb=15V, 0,1A, 0,063W, 9MHz	1a	Mat	ASY26..27, ASY48
2SA304	Ge-P	AM-ZF, 18V, Ueb=12V, 40MHz, 4,5MHz	2a	Tos	(AF124..127, AF200, 2SA102..104)
2SA305	Ge-P	AM-VM/O, 18V, Ueb=12V, 40mA, 10MHz	2a	Tos	(AF124..126, AF200, 2SA102..104)
2SA306	Ge-P	RF/IF AMP, 20V, 10mA, 400MHz	4g	old	AF124..126, AF200, 2SA103..104
2SA307	Ge-P	RF/IF AMP, 20V, 10mA, 400MHz	4g	old	AF124..126, AF200, 2SA103..104
2SA306	Ge-P	VHF/UHF, 20V, 5mA, 450MHz	1g	Mat	AF139, AF239(S)
2SA309	Ge-P	VHF/UHF, 20V, 5mA, 600MHz	1g	Mat	AF139, AF239(S)
2SA31	Ge-P	HF, 12V, 10mA, 5MHz	2a	Fui	AF124..127, AF200, 2SA201..203
2SA310	Ge-P	VHF/UHF, 32V, 25mA, 650MHz	1g	Mat	AF139, AF239(S)
2SA311	Ge-P	S, 40V, 0,4A, 0,15W, 50MHz, -/330ns	2a	Tos	ASY76..77
2SA312	Ge-P	S, 40V, 0,2A, 0,15W, 50MHz, -/320ns	2a	Tos	ASY48, ASY76..77
2SA313	Ge-P	AM-V/M/O, 18V, 20mA, 40MHz	2a	Tos	AF124..126, AF200, 2SA103..104
2SA314	Ge-P	AM-V/M/O, 18V, 20mA, 40MHz	2a	Tos	AF124..126, AF200, 2SA103..104
2SA315	Ge-P	AM-V/M/O, 18V, 20mA, 55MHz	2a	Tos	AF124..126, AF200, 2SA103..104
2SA316	Ge-P	AM-V/M/O, 18V, 20mA, 75MHz	2a	Tos	AF124..126, AF200, 2SA103..104
2SA32	Ge-P	HF/ZF, 20V, Ueb=10V, 50mA, 10MHz	2a	Fui	(AF121S, AF202(S), AFY18)
2SA321	Ge-P	AM-V/M/O/ZF, 20V, 300mA, 30MHz	2a	Say	AF124..126, AF200, 2SA103..104
2SA322	Ge-P	AM-V/M/O/ZF, 20V, 300mA, 35MHz	2a	Say	AF124..126, AF200, 2SA103..104
2SA323	Ge-P	RF/IF AMP, 20V, 10mA, 400MHz	4g	Say	AF124..126, AF200, 2SA103..104
2SA324	Ge-P	RF/IF AMP, 15V, 50mA, 250MHz	2a	Say	AF124..126, AF200, 2SA103..104
2SA325	Ge-P	S, 20V, Ueb=15V, 0,08A, 0,06W, 5MHz	2a	old	ASY26..27, ASY48
2SA326	Ge-P	S, 20V, Ueb=15V, 0,08A, 0,08W, 10MHz	2a	old	ASY26..27, ASY48
2SA327	Ge-P	RF/IF AMP, 15V, 50mA, 250MHz	2a	old	ASY48, 2N2955..2957
2SA328	Ge-P	RF/IF AMP, 20V, 10mA, 400MHz	4g	Say	AF124..127, AF200, 2SA101..104
2SA329	Ge-P	HF/ZF, 20V, 10mA, 5,5MHz	2a	Say	AF124..127, AF200, 2SA102..104
2SA33	Ge-P	HF/ZF, 20V, Ueb=10V, 25mA, 8MHz	2a	Fui	(AF121S, AF202(S), AFY18)
2SA330	Ge-P	HF/ZF, 20V, 10mA	2a	Say	AF124..127, AF200, 2SA102..104
2SA331	Ge-P	HF/ZF, 40V, 50mA, >40MHz	2a	Say	AF124..127, AF200, 2SA103..104
2SA332	Ge-P	RF/IF AMP, 20V, 10mA, 400MHz	4g	Say	AF124..126, AF200, 2SA104
2SA333	Ge-P	RF/IF AMP, 20V, 10mA, 400MHz	4g	Say	AF124..126, AF200, 2SA104
2SA334	Ge-P	RF/IF AMP, 20V, 10mA, 400MHz	4g	Say	AF124..126, AF200, 2SA104
2SA336	Ge-P	RF/IF AMP, 20V, 10mA, 400MHz	4g	Hit	AF124..127, AF200, 2SA102..104
2SA337	Ge-P	AM-V/M/O, 9V, 10mA, 35MHz	4g	Hit	AF124..126, AF200, 2SA102..104
2SA338	Ge-P	HF, 20V, 5mA, 15MHz	37a	Mat	AF124..127, AF200, 2SA101..104
2SA339	Ge-P	HF, 20V, 5mA, 30MHz	37a	Mat	AF124..127, AF200, 2SA101..104
2SA340	Ge-P	FM-V/M/O, 20V, 10mA, 70MHz	5g	Mat	AF124..125, AF200, 2SA260..265
2SA341	Ge-P	FM-V/M/O, 20V, 10mA, 70MHz	5g	Mat	AF124..125, AF200, 2SA260..265
2SA342	Ge-P	FM-V/M/O, 20V, 100mA, 100MHz	5g	Mat	AF124..125, AF200, 2SA260..265
2SA343	Ge-P	FM/VHF, 20V, 5mA, 100MHz	1g	Mat	AF106, AF109R, AF139, AF239(S)
2SA344	Ge-P	RF/IF AMP, 15V, 50mA, 250MHz	2a	Mat	AF124..125, AF106, AF109R, 2SA342
2SA345	Ge-P	FM/VHF, 20V, 10mA, >250MHz	5g	Mit	AF109R, AF139, AF239(S), 2SA260..265
2SA348	Ge-P	FM/VHF, 20V, 10mA, >250MHz	5g	Mit	AF109R, AF139, AF239(S), 2SA260..265
2SA347	Ge-P	FM/VHF, 20V, 10mA, >250MHz	5g	Mit	AF109R, AF139, AF239(S), 2SA260..265
2SA348	Ge-P	FM, 20V, 10mA, >200MHz	5g	Mit	AF106, AF109R, AF139, AF239(S)
2SA349	Ge-P	FM, 20V, 10mA, >100MHz	5g	Mit	AF106, AF109R, AF139, AF239(S)
2SA35	Ge-P	HF, 16V, 15mA, 10MHz	2a	Fui	AF124..127, AF200, 2SA201..202
2SA350(A,H)	Ge-P	AM-V/M/O, 20(H=30)V, 10mA, 40MHz	2a	Hit	AF124..126, AF200, 2SA216..227
2SA351(A,B)	Ge-P	AM-V/M/O, 20V, 10mA, 40MHz	2a	Hit	AF124..126, AF200, 2SA218..227
2SA352(A,B)	Ge-P	AM-V/M/O, 20V, 10mA, 40MHz	2a	Hit	AF124..126, AF200, 2SA216..227
2SA353(A)	Ge-P	AM-ZF, 25(A=50)V, 10mA, 30MHz	2a	Hit	AF124..127, AF200, 2SA218..227
2SA354(A)	Ge-P	AM-V/M/O, 25(A=50)V, 10mA, 30MHz	2a	Hit	AF124..126, AF200, 2SA218..227
2SA355(A)	Ge-P	AM-V/M/O, 25(A=50)V, 10mA, 30MHz	2a	Hit	AF124..126, AF200, 2SA218..227
2SA356	Ge-P	AM-ZF, 9V, 10mA, 25MHz	2a	Hit	AF124..127, AF200, 2SA218..227
2SA357	Ge-P	AM-V/M/O, 9V, 10mA, 30MHz	2a	Hit	AF124..126, AF200, 2SA218..227

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2SA358	Ge-P	HF,75V,50mA,40MHz	2a*	Hit	AF118,SFT162
2SA359	Ge-P	VHF,20V,20mA,300MHz	2a	Say	AF109R,AF139,AF239(S)
2SA36	Ge-P	ZF,16V,15mA,5MHz	2a	Fui	AF124..127,AF200,2SA201..203
2SA360	Ge-P	RF/IF AMP,20V,10mA,400MHz	4g	Mit	AF124..125,AF200,2SA342
2SA361	Ge-P	RF/IF AMP,20V,10mA,400MHz	4g	Mit	AF124..125,AF200,2SA342
2SA362	Ge-P	RF/IF AMP,20V,10mA,400MHz	4g	Mit	AF124..125,AF200,AF106,AF109R
2SA363	Ge-P	RF/IF AMP,20V,10mA,400MHz	4g	Mit	ASZ21,2N2955..2957
2SA364	Ge-P	RF/IF AMP,15V,50mA,250MHz	2a	Mit	AF124..126,AF200,2SA218..227
2SA365	Ge-P	RF/IF AMP,15V,50mA,250MHz	2a	Mit	AF124..126,AF200,2SA218..227
2SA366	Ge-P	RF/IF AMP,15V,50mA,250MHz	2a	Mit	AF124..126,AF200,2SA218..227
2SA367	Ge-P	AM-V/M/O,20V,10mA,30MHz	2a	Mit	AF124..126,AF200,2SA218..227
2SA368	Ge-P	AM-V/M/O,20V,10mA,40MHz	2a	Mit	AF124..126,AF200,2SA218..227
2SA369	Ge-P	AM-V/M/O,20V,10mA,50MHz	2a	Mit	AF124..126,AF200,2SA218..227
2SA37	Ge-P	HF,18V,Ueb=12V,5mA,7MHz	2a	Tos	(AF124..127,AF200)
2SA370	Ge-P	HF,75V,50mA,40MHz	2a*	Mit	AF118,SFT162,2SA358
2SA371	Ge-P	S,20V,Ueb=12V,15mA,0,08W,10,5MHz	2a	Mit	ASY26..27,ASY48
2SA372	Ge-P	SS,15V,0,2A,0,1W,>350MHz,6/45ns	2a	Tos	—
2SA373(A)	Ge-P	VHF-Tr,25V,0,15A,0,25W,400MH	2a	Hit	—
2SA374	Ge-P	VHF-Tr,34V,0,3A,300MHz	2a	Mat	—
2SA375	Ge-P	HF-O/Tr/S,30V,0,1A,0,08W,40MH	2a	Mit	(ASY26..27,ASY48)
2SA376	Ge-P	FM,22V,10mA	5g	Son	AF124..125,AF106,AF109R,2SA342
2SA377	Ge-P	VHF,20V,5mA,200MHz	5g	Mat	AF109R,AF139,AF239(S)
2SA378	Ge-P	VHF,20V,5mA,250MHz	5g	Mat	AF109R,AF139,AF239(S)
2SA379	Ge-P	VHF,20V,5mA,300MHz	5g	Mat	AF109R,AF139,AF239(S)
2SA36	Ge-P	AM-ZF,18V,Ueb=12V,5mA,10MHz	2a	Tos	(AF124..127,AF200)
2SA360	Ge-P	AM-M/ZF,25V,10mA,60MHz	2a	old	AF124..126,AF200,2SA218..227
2SA361	Ge-P	AM-O,25V,10mA,35MHz	2a	old	AF124..126,AF200,2SA218..227
2SA362	Ge-P	AM-M,25V,10mA,30MHz	2a	old	AF124..126,AF200,2SA218..227
2SA363	Ge-P	AM-V/M,25V,10mA,25MHz	2a	old	AF124..126,AF200,2SA218..227
2SA384	Ge-P	AM-V/M/ZF,25V,10mA,40MHz	2a	old	AF124..126,AF200,2SA218..227
2SA365	Ge-P	HF/S,16V,Ueb=10V,10mA,10MHz	2a	Mat	ASY26..27,(AF124..127,AF200)
2SA368	Ge-P	VHF-Tr/O,32V,0,3A,350MHz	2a	Mat	—
2SA367	Ge-P	AM-ZF,10V,15mA	2a	Say	AF124..127,AF200,2SA218..227
2SA369	Ge-P	UHF,20V,10mA,600MHz	5g	Hit	AF139,AF239(S)
2SA39	Ge-P	AM-ZF,18V,Ueb=12V,5mA,5,5MHz	2a	Tos	(AF124..127,AF200)
2SA390	Ge-P	UHF,20V,10mA,700MHz	5g	Hit	AF136,AF239(S)
2SA391	Ge-P	HF,18V,Ueb=12V,0,2A,0,15W,7MHz	2a	Oki	ASY26..27
2SA392	Ge-P	HF,18V,Ueb=12V,0,2A,0,15W,11MHz	2a	Oki	ASY26..27
2SA393	Ge-P	HF,18V,Ueb=12V,0,2A,0,15W,16MHz	2a	Oki	ASY26..27
2SA393A	Ge-P	=2SA393: 30V	2a	Oki	ASY26
2SA394	Ge-P	HF,18V,Ueb=12V,0,2A,0,15W,22MHz	2a	Oki	ASY26..27
2SA395	Ge-P	HF,18V,Ueb=12V,0,2A,0,15W,29MHz	2a	Oki	ASY26..27
2SA396	Ge-P	HF,15V,Ueb=15V,0,2A,0,2W,6MHz	2a	Oki	ASY26..27
2SA397	Ge-P	HF,23V,Ueb=15V,0,2A,0,2W,8MHz	2a	Oki	ASY26..27
2SA398	Ge-P	HF,30V,Ueb=20V,0,2A,0,2W,10MHz	2a	Oki	ASY26
2SA399	Ge-P	HF,30V,Ueb=20V,0,2A,0,2W,12MHz	2a	Oki	ASY26
2SA40	Ge-P	S,25V,Ueb=12V,0,05A,5MHz	2a	Fui	ASY26..27,ASY48
2SA400	Ge-P	RF/IF AMP,15V,50mA,250MHz	2a	Fui	AF124..126,AF200,2SA218..227
2SA401	Ge-P	RF/IF AMP,15V,50mA,250MHz	2a	Hit	AF121(S),AF202(S)
2SA402	Si-P	Uni,35V,0,1A,0,25W,200MHz	2a	Say,Tos	BC213,BC258,BC308,BC558,++
2SA403	Ge-P	FM/VHF,20V,5mA,260MHz	2a	Nec	AF109R,AF139,AF239(S)
2SA404	Ge-P	FM/VHF,20V,5mA,400MHz	5g	Nec	AF109R,AF139,AF239(S)
2SA405	Ge-P	S,15V,0,05A,0,15W,50/110ns	2a	Nec	ASZ21,2N2955..2957
2SA406	Ge-P	S,30V,Ueb=20V,0,2A,0,2W,9MHz	2a	Nec	ASY26,ASY48
2SA407	Ge-P	S,30V,Ueb=20V,0,2A,0,2W,14MHz	2a	Nec	ASY26,ASY48
2SA408	Ge-P	S,15V,Ueb=15V,0,05A,0,05W,50MHz	2a	Fui	ASZ21,2N2955..2957
2SA409	Ge-P	S,15V,Ueb=15V,0,05A,0,05W,80MHz	2a	Fui	ASZ21,2N2955..2957
2SA41(H)	Ge-P	HF,35V,Ueb=20V,40mA,6MHz	2a*	Hit	(ASY26..27,ASY48)
2SA410	Ge-P	SS,12V,0,15A,0,15W,25/90ns	2a	Nec	ASZ21,2N2955..2957
2SA411	Ge-P	SS,15V,0,15A,0,15W,25/75ns	2a	Nec	ASZ21,2N2955..2957
2SA412	Ge-P	HF/S,13V,0,1A,0,15W,40MHz	2a	Hit	AFY18,2N3323..3325
2SA413	Ge-P	SS,20V,0,03A,0,1W,50/80ns	2a	Mat	ASZ21,2N2635,2N2955..2957
2SA414	Ge-P	S,30V,Ueb=20V,0,2A,0,15W,320/1300ns	2a	Mat	ASY26,ASY48
2SA415	Ge-P	S,25V,Ueb=20V,0,2A,0,15W,265/1300ns	2a	Mat	ASY26..27,ASY48
2SA416	Ge-P	S-L,70V,0,7A,8W,350/800MHz	23a	Mat	(AUY10)
2SA417	Ge-P	S,15V,0,2A,0,15W,<70/100ns	2a	Nec	2N2955..2957

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2SA419	Ge-P	VHF, 20V, 5mA, >350MHz	5g	Say	AF139, AF239(S)
2SA42(H)	Ge-P	HF, 45V, Ueb=20V, 40mA, 6MHz	2a*	Hit	(ASY26..27, ASY46)
2SA420	Ge-P	VHF, 20V, 5mA, >300MHz	5g	Say	AF139, AF239(S)
2SA421	Ge-P	UHF, 20V, 5mA, 660MHz	5g	Say	AF139, AF239(S)
2SA422	Ge-P	UHF, 20V, 5mA, 680MHz	5g	Say	AF139, AF239(S)
2SA423	Ge-P	UHF, 20V, 5mA	5g	Say	AF139, AF239(S)
2SA424	Ge-P	UHF, 20V, 5mA	5g	Say	AF139, AF239(S)
2SA425	Ge-P	VHF, 30V, 30mA, 350MHz	5g	old	AF139, AF239(S)
2SA426	Ge-P	VHF, 30V, 30mA, 500MHz	5g	old	AF139, AF239(S)
2SA427	Ge-P	RF/IFAMP, 15V, 50mA, 250MHz	2a	Say	AF124..126, AF200, 2SA340..342
2SA428	Ge-P	RF/IFAMP, 15V, 50mA, 250MHz	2a	Say	AF124..126, AF200, 2SA340..342
2SA429(G,GTM)	Si-P	Nix, Vid, 150V, 0,03A, 100MHz	7c	Tos	BF398, BF421, BF423, BF435..437, ++
2SA43	Ge-P	RF/IFAMP, 15V, 50mA, 250MHz	2a	Fui	AF124..126, AF200, 2SA103..104
2SA430	Ge-P	UHF, 20V, 5mA, >450MHz	5g	Tos	AF139, AF239(S)
2SA431(A)	Ge-P	VHF, 20V, 5mA, 500MHz	5g	Tos	AF139, AF239(S)
2SA432(A)	Ge-P	VHF, 20V, 5mA, 450MHz	5g	Tos	AF139, AF239(S)
2SA433	Ge-P	RF/IFAMP, 20V, 10mA, 400MHz	4g	Tos	AF124..126, AF200, 2SA216..227
2SA434	Ge-P	FM/VHF, 20V, 10mA, 660MHz	1g	Hit	AF109R, AF139, AF239(S)
2SA435	Ge-P	FM/VHF, 20V, 10mA, 330MHz	5g	Hit	AF109R, AF139, AF239(S)
2SA436	Ge-P	FM/VHF, 20V, 10mA, 400MHz	5g	Hit	AF109R, AF139, AF239(S)
2SA437	Ge-P	FM/VHF, 20V, 10mA, 400MHz	5g	Hit	AF109R, AF139, AF239(S)
2SA438	Ge-P	FM/VHF, 20V, 10mA, 520MHz	5g	Hit	AF109R, AF139, AF239(S)
2SA439				Say	—
2SA44	Ge-P	HF/ZF, 15V, Ueb=10V, 10mA, 15MHz	1a	Mat	(AF124..127, AF200, 2SA201..202)
2SA440(A)	Ge-P	FM/VHF, 20V, 5mA, 350MHz	5g	Say	AF109R, AF139, AF239(S)
2SA441	Ge-P	FM/VHF, 20V, 10mA, 500MHz	2a	Say	AF109R, AF139, AF239(S)
2SA442				Say	—
2SA443	Ge-P	Dual, Chopper, 21V, 15mA, 25MHz		Hit	—
2SA444	Ge-P	S+integr. Diode, 16V, 12mA, 12MHz		Hit	—
2SA445	Ge-P	Dual, 16V, 15mA, 10MHz		Hit	—
2SA446	Ge-P	SS, 15V, 0,2A, 0,2W, 20/145ns	2a	Tos	2N2955..57
2SA447	Ge-P	VHF/UHF, 25V, 15mA, 650MHz	5g	Mat	AF139, AF239(S)
2SA448	Ge-P	UHF, 15V, 5mA, 1700MHz	5g	Son	2N5043, (AF239S)
2SA449	Ge-P	SS, 10V, 0,1A, 0,15W, <80/120ns	2a	Hit	ASZ21, 2N2955..2957
2SA45	Ge-P	AM-ZF, 16V, Ueb=12V, 5mA	2a	Tos	(AF124..127, AF200, 2SA201..203)
2SA450(H)	Ge-P	SS, 12V, 0,1A, 0,15W, <60/95ns	2a	Hit	ASZ21, 2N2955..2957
2SA451(H)	Ge-P	SS, 12V, 0,1A, 0,15W, <60/110ns	2a	Hit	ASZ21, 2N2955..2957
2SA452(H)	Ge-P	SS, 12V, 0,1A, 0,15W, <80/120ns	2a	Hit	ASZ21, 2N2955..2957
2SA453	Ge-P	FM/VHF, 22V, 10mA, 630MHz	5g	Son	AF109R, AF139, AF239(S)
2SA454	Ge-P	FM/VHF, 22V, 10mA, 630MHz	5g	Son	AF109R, AF139, AF239(S)
2SA455	Ge-P	FM/VHF, 22V, 10mA, 630MHz	5g	Son	AF109R, AF139, AF239(S)
2SA456	Ge-P	FM/VHF, 22V, 10mA, 630MHz	5g	Son	AF109R, AF139, AF239(S)
2SA457	Ge-P	RF/IFAMP, 15V, 50mA, 250MHz	2a	Tos	AF124..126, AF200, 2SA216..227
2SA458	Ge-P	S, 25V, 0,2A, 0,15W, <1000/700ns, B=60	2a	Mit	ASY26..27, ASY46
2SA459	Ge-P	=2SA456: B=120	2a	Mit	ASY26..27, ASY48
2SA46	Ge-P	HF/ZF, 12V, 25mA, 10MHz	2a	Fui	AF124..127, AF200, 2SA201..202
2SA460	Ge-P	RF/IFAMP, 20V, 10mA, 400MHz	4g	Mit	AF109R, AF139, AF239(S)
2SA461	Ge-P	RF/IFAMP, 20V, 10mA, 400MHz	4g	Mit	AF109R, AF139, AF239(S)
2SA462	Ge-P	RF/IFAMP, 20V, 10mA, 400MHz	4g	Mit	AF109R, AF139, AF239(S)
2SA463	Ge-P	RF/IFAMP, 20V, 10mA, 400MHz	4g	Mit	AF109R, AF139, AF239(S)
2SA464	Ge-P	RF/IFAMP, 20V, 10mA, 400MHz	4g	Mit	AF139, AF239(S)
2SA465	Ge-P	UHF, 20V, 5mA, 600MHz	5g	Mat	AF139, AF239(S)
2SA466	Ge-P	HF, 16V, 10mA, 15MHz	2a	Tos	AF124..127, AF200, 2SA216..227
2SA467(G,GTM)	Si-P	Uni, 40V, 0,4A, 0,3W, 200MHz	7c	Tos	BC327, BC638, BC638, BC640, ++
2SA466	Ge-P	AM-VM/O, 16V, 10mA, 45MHz	2a	Tos	AF124..126, AF200, 2SA220..227
2SA469	Ge-P	AM-VM/O, 16V, 10mA, 30MHz	2e	Tos	AF124..126, AF200, 2SA220..227
2SA47	Ge-P	HF/ZF, 12V, 25mA, 6MHz	2a	Fui	AF124..127, AF200, 2SA201..203
2SA470	Ge-P	AM-VM/O, 18V, 10mA, 35MHz	2a	Tos	AF124..126, AF200, 2SA220..227
2SA471	Ge-P	FM-ZF, 16V, 10mA, 35MHz	2a	Tos	AF124..126, AF200, 2SA220..227
2SA472	Ge-P	AM-V/M/O/ZF, 18V, 10mA, 35MHz	2a	Tos	AF124..126, AF200, 2SA220..227
2SA473	Si-P	NF/S-L, 30V, 3A, 10W, 100MHz	17j	Mic, Tos	2SA1012, 2SB1273, 2SA1288..1289
2SA474	Ge-P	HF, 50V, 0,05A, 0,12W, 70MHz	2a	Tos	(AF121(S), AF202(S))
2SA475	Ge-P	HF, 20V, 0,05A, 0,12W, 30MHz	2a	Tos	(AF121(S), AF202(S))
2SA476	Ge-P	HF, 18V, 10mA, 130MHz	2a	Tos	AF106, AF109R, 2SA345..349
2SA477	Ge-P	FM-ZF, 16V, 10mA, 45MHz	2a	Tos	AF124..126, AF200, 2SA218..227
2SA478	Ge-P	S, 40V, 0,4A, 0,125W, >25MHz, -/335ns	2a	Tos	2N705, 2N960..967, 2N2955..2957

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2SA479	Ge-P	S, 40V, 0,2A, 0,125W, >25MHz, -/<370ns	2a	Tos	2N705, 2N960..967, 2N2955..2957
2SA48	Ge-P	AM-VM/O, 18V, Ueb=12V, 5mA	2a	Tos	(AF124..127, AF200, 2SA201..203)
2SA480	Si-P	AM/FM, 30V, 100mA, 70MHz	2a	Son	BF324, BF440..441, BF450..451, ++
2SA481				Tos	—
2SA482	Si-P	Uni, 40V, 0,6A, 0,6W, 70MHz	2a	Tos	BC160..181, BC303..304, 2N2904..05, ++
2SA483	Si-P	S-L, TV-VA, 150V, 1,5A, 20W, 10MHz	22a	Tos	2SA839, 2SA940, 23B628(A), 2SB861, ++
2SA484	Si-P	Uni, 110V, 1,5A, 0,8W, 20MHz	2a	Tos	BCX80, 2N3634..3637
2SA485	Si-P	=2SA484: 80V	2a	Tos	BCX60, BSV17, BSS17..18, 2N5322..23
2SA486	Si-P	≈2SA484: 50V	2a	Tos	BCX60, BSV16..17, 2N5322..5323, ++
2SA487				Tos	—
2SA488				Tos	—
2SA489	Si-P	NF/S-L, 70V, 4A, 30W, >3MHz	17j	Mic, Tos	BD244A, BD538, BD540B, BD952, ++
2SA49	Ge-P	AM-ZF, 18V, Ueb=12V, 5mA, 9MHz	2a	Tos	(AF124..127, AF200, 2SA201..203)
2SA490	Si-P	NF/S-L, 50V, 3A, 25W, >3MHz	17j	Mic, Tos	BD242, BD244, BD536, BD936, ++
2SA491				Tos	—
2SA492				Tos	—
2SA493(GTM)	Si-P	Uni, ra, 50V, 0,05A, 0,2W, 80MHz	7c	Tos	BC214, BC416, BC560, 2SA1136..1137
2SA494	Si-P	Uni, ra, 36V, 0,03A, 0,2W, 200MHz	7c	Tos	BC214, BC259, BC309, BC559, 2SA1137+
2SA495(GTM)	Si-P	Uni, 36V, 0,1A, 0,2W, 200MHz	7c	Tos	BC213, BC257, BC307, BC557, 2SB725++
2SA496	Si-P	Uni-L, 40V, 1A, 5W, 100MHz	14h	Tos	BD136, BD227, BD376, 2SB1009
2SA497	Si-P	Uni, 60V, 0,6A, 0,6W, 70MHz	2a	Tos, Mic	BC303, BCX80, BSV17, 2N3634..36, ++
2SA496	Si-P	=2SA497: 50V	2a	Tos, Mic	BC161, BC303..304, BCX60, BSV16, ++
2SA499(M)	Si-P	HF/S, 50V, 0,1A, 0,25W, 250MHz	2a	Tos, Mic	BC212, BC257, BC307, BC557, ++
2SA50	Ge-P	S, 18V, Ueb=12V, 24mA, 14MHz	2a	Tos	ASY26..27, ASY48
2SA500(M)	Si-P	=2SA499: 30V	2a	Tos	BC213, BC258, BC308, BC558, 2N3906++
2SA500D	Si-P	=2SA499: 35V	2a		BC213, BC258, BC308, BC558, ++
2SA501	Si-P	Uni, 40V, 0,2A, 0,75W, 200MHz	2a	Tos	BC160..181, BC303..304, 2N2303, ++
2SA502	Si-P	Nix, 90V, 0,1A, 0,3W, >50MHz	7c	Tos	BF397..398, BSS68, 2SA970, 2SA1285, ++
2SA503(M)	Si-P	Uni, 100V, 0,6A, 0,8W, 60/530ns	2a	Tos, Mic	BCX80, BSW40
2SA504(M)	Si-P	=2SA503: 80V	2a		BC303, BCX60, BSW40, 2N4036, ++
2SA505	Si-P	Uni-L, 60V, 1A, 5W, 100MHz	14h	Tos	BD136, BD229, BD378, 2SB744(A), ++
2SA506	Ge-P	VHF, 20V, 5mA, 300MHz	5g	Tos	AF109R, AF139, AF239(S)
2SA507	Ge-P	VHF, 20V, 5mA, 250MHz	5g	Tos	AF109R, AF139, AF239(S)
2SA506	Ge-P	VHF, 20V, 5mA, 200MHz	5g	Tos	AF109R, AF139, AF239(S)
2SA509	Si-P	Uni, 35V, 0,5A, 0,6W, 140MHz	9b	Tos	BC327, BC636, BC636, 2SA1515, ++
2SA509GTM	Si-P	=2SA509:	7c		→2SA509
2SA51	Ge-P	AM-V/M/O, 18V, Ueb=12V, 5mA, 14MHz	2a	Tos	(AF124..127, AF200, 2SA202)
2SA510(M)	Si-P	NF/HF/S, 120V, 1,5A, 0,8W, 80MHz	2a	Tos	2N3634..3637
2SA511	Si-P	=2SA510: 90V	2a	Tos	BCX60, BSS17, BSV17, 2N5322
2SA512(M)	Si-P	≈2SA510: 80V	2a	Tos	BCX80, BSS17..18, 2N5322..5323, ++
2SA513	Si-P	≈2SA510: 60V	2a	Tos	BC181, BCX80, BSV18, 2N5322..523, ++
2SA514				Tos	—
2SA515				Tos	—
2SA516(N)	Si-P	Uni, 60V, 1,5A, 0,8W, 50MHz	2a	Tos	BCX60, BSS17..18, 2N5322..5323, ++
2SA516A	Si-P	=2SA518: 120V	2a		2N3634..3637
2SA517	Ge-P	HF, 18V, 10mA, 80MHz	2a	Tos	AF124..126, AF200, 2SA218..227
2SA518	Ge-P	HF, 18V, 10mA, 45MHz	2a	Tos	AF124..126, AF200, 2SA218..227
2SA519				Say	—
2SA52	Ge-P	AM-ZF, 18V, Ueb=12V, 5mA, 9MHz	2a	Tos	(AF124..127, AF200, 2SA201..202)
2SA520				Say	—
2SA521				Say	—
2SA522(N)	Si-P	Uni, 25V, 0,1A, 0,25W, 200MHz	2a	Fui, Tos	BC213, BC258, BC308, BC558, ++
2SA522A	Si-P	=2SA522: 50V	2a		BC212, BC257, BC307, BC557, ++
2SA523(N)	Si-P	Uni, 40V, 0,3A, 0,65W, 200MHz	2a	Fui	BC160..181, BC303..304, 2N2904..05, ++
2SA523A	Si-P	=2SA523: 60V	2a		BC161, BC303..304, 2N2904..2905, ++
2SA524	Si-P	Uni, 25V, 0,1A, 0,35W, 250MHz	2a	Fui	BC213, BC258, BC308, BC558, ++
2SA525	Ge-P	FM/VHF, 20V, 5mA, 250MHz	5g	Tos	AF109R, AF139, AF239(S)
2SA526	Si-P	Uni, 50V, 1A, 0,5W	2a	Son	BC181, BSV18..17, 2N2904..2905, ++
2SA527	Si-P	HF/S, 50V, 2A, 5W, 80MHz	43m	Son	(BD510, BD518, BD526, BD376, ++)
2SA528	Si-P	HF/S, 50V, 2A, 5W, 80MHz	43m	Son	(BD510, BD518, BD526, BD376, ++)
2SA529	Si-P	HF/S, 50V, 1A, 5W(Tc=25°)	2a	Son	BC161, BSV16..17, 2N2904..2905, ++
2SA53	Ge-P	AM-ZF, 18V, Ueb=12V, 5mA, 7MHz	2a	Tos	(AF124..127, AF200, 2SA201..202)
2SA530(H)	Si-P	S, 50V, 0,1A, 0,2W, 90/160ns	2a	Hit	BC557, BSW24, 2N2906..07, 2N3250..51++
2SA531(H)	Si-P	60V, 0,4A, 0,6W	2a	Hit	—
2SA532	Si-P	Uni, 50V, 0,2A, 0,5W, 90MHz	2a	Say, Mic	BC161, BSV18..17, 2N2904..2905, ++
2SA532-3	Si-P	=2SA532: 75V	2a		BC181, BSV18..17, 2N2904..2905, ++

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2SA532-4	Si-P	=2SA532: 50V	2a		BC161, BSV16..17, 2N2904..2905,++
2SA535	Si-P	Uni, 75V, 0,7A, 0,5W, 80MHz	2a	Say	BC303, BSV17, BSW40, 2N3634..37,++
2SA536	Si-P	=2SA536: 50V	2a	Say	BC161, BC303..304, 2N2904..2905,++
2SA537(H)	Si-P	S, 80V, 0,7A, 0,75W, 150MHz, <50/360ns	2a	Hit	BSW40, 2N4030..4033, 2N4036..4037,++
2SA537A	Si-P	=2SA536: 100V	2a		BSW40
2SA538	Ge-P	HF/S, 25V, Ueb=12V, 0,05A, 0,12W, 6MHz	2a	Tos	ASY26..27, ASY48
2SA539(S)	Si-P	Uni, 80V, 0,2A, 0,25W, 160MHz	7c	Mic, Nec	BC212, BC256, BC266, BC556,++
2SA54	Ge-P	VHF, 20V, 5mA, 400MHz	5g	Nec	AF109R, AF139, AF239(S)
2SA542	Si-P	Uni, 30V, 0,05A, 0,15W, >30MHz	24b	Nec	(BC213, BC258, BC308, BC558,++)
2SA543	Si-P	=2SA542: ra	24b	Nec	(BC214, BC259, BC309, BC559,++)
2SA544	Si-P	Uni/S, 60V, 0,2A, 0,75W, <50/250ns	2a	Nec, Mic	BC161, BC303..304, 2N2904..2905,++
2SA545	Si-P	Uni, 70V, 0,2A, 0,4W, 180MHz	7c°	Nec, Mic	BC640, 2SB647, 2SB910, 2SB1041,++
2SA546(Z)	Si-P	Uni, 70V, 1A, 0,75W, 80MHz	2a	Mat	BCX60, BSS17..18, 2N5322..5323,++
2SA546A	Si-P	=2SA546: 90V	2a		BCX60, BSS17, 2N5322
2SA547(Z)	Si-P	=2SA546: 10W	43m	Mat	(BD520, BD528, BD530, BD378)
2SA547A	Si-P	=2SA546: 90V, 10W	43m		(BD530, BD380)
2SA548(H)	Si-P	HF/S, 50V, 0,1A, 0,2W, 90/160ns	2a	Hit	BC557, BSW24, 2N2906..07, 2N3250..51++
2SA549(H)	Si-P	Nix, S, 70V, 0,1A, 0,2W, >40MHz	2a	Hit	BC556, BF397..398, BSS68, 2SA970,++
2SA549A	Si-P	=2SA549: 150V, 0,05A	2a		BF398, BF435, 2SA1019, 2SA1285A,++
2SA55	Ge-P	HF, 15V, Ueb=10V, 10mA, 6MHz	1a	Mat	(AF124..127, AF200, 2SA201..203)
2SA550(Z)	Si-P	Uni, 25V, 0,1A, 0,3W, 120MHz	2a	Mat, Mic	BC213, BC256, BC306, BC558, 2SA1137+
2SA550A	Si-P	=2SA550: 45V	2a		BC212, BC257, BC307, BC557, 2SA1137+
2SA551	Si-P	Uni, 70V, 0,4A, 0,6W, 80MHz		Say	BC303, BC640, BSV17, 2SB647,++
2SA552	Si-P	HF/S, 60V, 0,2A, 0,75W, <100/300ns	2a	Nec	BSW23, 2N2904..2905, 2N3072..3073,++
2SA553	Si-P	Uni, 40V, 0,3A, 0,25W, 200MHz	2a	Fui	BC213, BC257, BC307, BC557,++
2SA554	Si-P	Uni, 25V, 0,3A, 0,25W, 200MHz	2a	Fui	BC213, BC258, BC308, BC558,++
2SA554A	Si-P	=2SA554: 40V	2a		BC213, BC257, BC307, BC557,++
2SA555	Si-P	Uni, 50V, 0,2A, 0,2W, 200MHz, -/195ns	7c	Fui	BC213, BC257, BC307, BC557,++
2SA556	Si-P	Uni, 20V, 0,2A, 0,2W, 200MHz	(7b)	Fui	BC213, BC258, BC308, BC558,++
2SA557	Si-P	Uni, 20V, 0,25A, 0,3W, 200MHz	8a	Fui	BC213, BC258, BC308, BC558,++
2SA558	Si-P	S, 40V, 0,2A, 0,35W, 200MHz, -/115ns	2a	Fui	BSW24, 2N2906..2907, 2N3905..3906,++
2SA559	Si-P	S, 20V, 0,2A, 0,35W, 200MHz, -/115ns	2a		BSW24, 2N2908..2907, 2N3905..3906,++
2SA559A	Si-P	=2SA559: 40V	2a		BSW24, 2N2906..2907, 2N3905..3906,++
2SA56	Ge-P	SS, 15V, 50mA, 300MHz, 50/110ns	2a	Nec	ASZ21, 2N2635, 2N2955..2957
2SA560(N)	Si-P	Uni, 80V, 0,8A, 0,8W, 150MHz	2a	Fui, Tos	BC303, BCX80, BSV17, 2N3634..37,++
2SA561	Si-P	Uni, 50V, 0,15A, 0,3W, 70MHz	7c	Tos	BC327, BC636, BC640, 2N2908..2907,++
2SA562(TM)	Si-P	Uni, 30V, 0,4A, 0,3W, 70MHz	7c	Tos	BC327..328, BC636, 2SA1515, 2SB910,++
2SA564(Z)	Si-P	Uni, 25V, 0,1A, 0,4W, 200MHz	7c	Mat, Mic	BC213, BC258, BC308, BC558,++
2SA564A(Z)	Si-P	=2SA564: 45V	7c		BC212, BC257, BC307, BC557,++
2SA565(K)	Si-P	Uni, 50V, 0,5A, 0,3W, 60MHz	2a	Hit	BC327, BC638, BC640, 2N2906..2907,++
2SA566(H)	Si-P	NF/HF/S-L, 100V, 0,7A, 10W, 100MHz	22a	Hit	2N5344..2SA913(A), 2SA985(A), 2SA1111,++
2SA567	Si-P	Uni, 30V, 0,1A, 0,2W, 70MHz	2a	Hit	BC213, BC258, BC308, BC558,++
2SA568	Si-P	Uni, 35V, 0,25A, 0,2W, 150MHz	7b	Mit	BC327, BC636, 2SA953, 2SA1515,++
2SA569	Si-P	=2SA568: 50V	7b	Mit	BC636, BC640, 2SB647, 2SB910, 2SB1041+
2SA57	Ge-P	RF/IF AMP, 20V, 10mA, 400MHz	4g	Tos	AF124..126, AF200, 2SA216..227
2SA570	Si-P	=2SA568: 65V	7b	Mit	BC638, BC640, 2SB647, 2SB910, 2B1041++
2SA571	Si-P	S, 80V, 1A, 0,6W, 300MHz, 25/110ns	2a	Nec	BSW40, 2N2904..2905, 2N4030..4033,++
2SA572				Njr	—
2SA573	Si-P	Uni, 30V, 0,1A, 0,3W, 150MHz	7c	Njr	BC213, BC256, BC308, BC558,++
2SA574	Si-P	=2SA573: 60V	7c	Njr	BC212, BC256, BC266, BC556,++
2SA575	Si-P	=2SA573: 90V	7c	Njr	2SA970, 2SA1049, 2SA1285(A), 2SA1136,++
2SA576	Si-P	Uni, 30V, 0,2A, 0,6W, 200MHz	8a	Njr	BC327..328, BC636, 2SA953, 2SA1515,++
2SA577	Si-P	Uni, 60V, 0,4A, 0,6W, 200MHz	8a	Njr	BC327A, BC636, BC640, 2N2906..907,++
2SA578	Si-P	Uni, ra, 50V, 0,03A, 0,3W, 180MHz	2a	Nec	BC214, BC416, BC560, 2SA1136..1137,++
2SA579	Si-P	=2SA578:	2a	Nec	→2SA576
2SA58	Ge-P	RF/IF AMP, 20V, 10mA, 400MHz	4g	Tos	AF124..126, AF200, 2SA218..227
2SA580	Si-P	Uni, 80V, 0,8A, 0,8W, 100MHz	2a	Fui	BC161, BC303..304, 2N2904..2905,++
2SA581	Si-P	=2SA580: 100V	2a	Fui	BC303, BCX80, BSW40, 2N3634..3637,++-
2SA587				Tos	—
2SA588				Tos	—
2SA589				Tos	—
2SA59	Ge-P	RF/IF AMP, 20V, 10mA, 400MHz	4g	Tos	AF124..126, AF200, 2SA218..227
2SA590				Tos	—
2SA591				Tos	—
2SA592				Tos	—
2SA593				Tos	—

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2SA594(M,N)	Si-P	HF/S,60V,0,2A,0,75W,200MHz	2a	Nec,Tos	BSW23,2N3072..3073,2N2904..2905,++
2SA595				Tos	—
2SA596				Tos	—
2SA597(N)	Si-P	HF/S,50V,1A,400MHz	2a	Tos	BSW40,2N2904..2905,2N4030..4033,++
2SA598				Tos	—
2SA599				Tos	—
2SA60	Ge-P	RF/IF AMP,15V,50mA,250MHz	2a	Tos	AF124..126,AF200,2SA218..227
2SA600				Tos	—
2SA601				Tos	—
2SA602				Tos	—
2SA603	Si-P	Uni,60V,0,2A,0,3W,250MHz	2a	Nec	BC212,BC556,BSW24,2N2906..2907,++
2SA604	Si-P	Nix,120V,0,03A,0,3W,170MHz	2a	Nec	BF396,BF423,BF435..437,2SA1370..72
2SA605	Si-P	Nix,160V,0,05A,0,3W,100MHz	2a	Nec	BF435..437,2SA1370..1372
2SA606(S)	Si-P	Uni,100V,0,7A,0,7W,100MHz	2a	Nec,Mic	BCX60,BSW40,2N3634..3637
2SA607(S)	Si-P	=2SA606:	43m	Nec	(BD380,BD530,2SA1014,2SB874..675)
2SA608	Si-P	Uni,30V,0,1A,0,1W,160MHz	7c	Say	BC213,BC258,BC308,BC558,++
2SA608K,KNP	Si-P	=2SA608: 55V,0,25W	7c		BC212,BC257,BC307,BC557,++
2SA608NP	Si-P	=2SA608: 40V,0,25W	7c		BC212,BC257,BC307,BC557,++-
2SA608SP	Si-P	=2SA608: 40V,0,2W	41c		BC212,BC257,BC307,BC557,++
2SA609	Si-P	Uni,30V,0,1A,0,1W,60MHz	7c	Say	BC213,BC258,BC308,BC558,++
2SA609NP	Si-P	=2SA609: 0,25W	7c		BC213,BC256,BC306,BC558,++
2SA609SP	Si-P	=2SA609: 0,2W	41c		BC213,BC258,BC308,BC558,++
2SA61	Ge-P	HF,20V,10mA,70MHz	2a	Mat	AF124..127,AF200,2SA216..227
2SA610	Si-P	Uni,30V,0,1A,0,15W,170MHz	7c	Njr	BC213,BC258,BC808,BC558,++
2SA611	Si-P	=2SA610: 60V	7c	Njr	BC212,BC256,BC266,BC556,++
2SA612	Si-P	Uni,90V,0,05A,0,2W,150MHz	≈2b	Njr	BF397.398,2SA693,2SA970,2SB715,++
2SA613	Si-P	NF/S-L,60V,1A,15W,30MHz	22a	Nec	BD240A,2SA748,2SA1111..1112,++
2SA614	Si-P	NF/S-L,60V,1A,15W,30MHz	22a	Nec	BD240B,2SA913,2SA1111..1112,++
2SA615	Si-P	NF/S-L,70V,3A,25W	22a	Nec	BD242A,BD538,BD938,BDX14,++
2SA616	Si-P	NF/S-L,80V,3A,25W,15MHz	22a	Nec	BD242B,BD538,BD938,BDX14,++
2SA617(K)	Si-P	Nix,150V,0,05A,0,2W,60MHz	2a	Hit	BF398,BF423,BF435..437,2SA1370,++
2SA616(K)	Si-P	=2SA617: 160V	2a	Hit	BF423,BF435..437,2SA1370..1372,++
2SA620	Si-P	Uni,ra,30V,0,05A,0,2W,120MHz	≈2b	Njr	BC214,BC259,BC308,BC559,++
2SA621	Si-P	Uni,60V,0,2A,0,4W,200MHz	2a	Njr	BC161,BC303..304,BSW23,2SA606,++
2SA622	Si-P-Darl	S,30V,0,3A,0,15W,B=40000	5c	Njr	BC516,BC876,BSR60..62,MPS-A75,++
2SA623	Si-P	NF/S-L,35V,1,5A,7W,70MHz	13n	Mit	(BD508,BD516,BD526,BD840,++)
2SA624	Si-P	=2SA623: 50V	13n	Mit	(BD510,BD516,BD526,BD842,++)
2SA625	Si-P	Uni,100V,0,5A,0,7W,100MHz	2a	Fui	BC461,BCX60,2SA606
2SA626	Si-P	NF/S-L,60V,5A,60W,15MHz	23a	Nec	BD246B,BD314,2N6226,2SB775..776,++
2SA627	Si-P	=2SA626: 100V	23a	Nec	BD246C,BD316,2N6226,2SB775..776,++
2SA628	Si-P	Uni,30V,0,1A,0,15W,100MHz	7b	Mit	BC213,BC256,BC308,BC558,++
2SA628A	Si-P	=2SA626: 60V	7b		BC212,BC256,BC266,BC556,++
2SA629	Si-P	Uni,ra,30V,0,03A,0,15W,100MHz	7b	Mit	BC213,BC259,BC309,BC559,++
2SA630				Hit	—
2SA631	Ge-P	HF,40V,0,05A,>40MHz	2a	Hit	(AF121(S),AF202(S),AFY18)
2SA632				Hit	—
2SA633	Si-P	NF/S-L,30V,2A,10W,60MHz	13j	Nec	2SA699,(BD430,BD614,BD614,++)
2SA634	Si-P	NF/S-L,40V,3A,10W,55MHz	13j	Nec	(BD616,BD616,BD620)
2SA635	Si-P	NF/S-L,60V,1A,10W,50MHz	13j	Nec	2SA887,(BD386,BD418,BD828,++)
2SA638	Si-P	NF/S-L,70/45V,3A,10W,45MHz	13j	Nec	(BD620)
2SA636A	Si-P	=2SA636: 70/60V	13j		(BD620)
2SA637	Si-P	Nix,150V,0,05A,0,3W,150MHz	2a	Mat,Mic	BF398,BF423,BF435..437,2SA1370,++
2SA638(S)	Si-P	Nix,150V,0,05A,0,25W,130MHz	7c	Nec	BF398,BF423,BF435..437,2SA1370,++
2SA639(S)	Si-P	=2SA638: 180V	7c	Nec	BF423,BF435..437,2SA1370..1372,++
2SA64	Ge-P	S,16V,0,04A,15MHz,-/1650ns	2a	Ful	ASY26..27,A8Y46
2SA840	Si-P	Uni,ra,50V,0,03A,0,25W,100MHz	7c	Nec	BC214,BC416,BC560,2SA1138..1137,++
2SA841	Si-P	Uni,50V,0,03A,0,25W,100MHz	7c	Nec	BC212,BC256,BC266,BC558,++
2SA842	Si-P	Uni,30V,0,2A,0,25W,200MHz	7c	Nec,Mic	BC327..326,BC638,BC638,BC840,++
2SA643	Si-P	Uni,40V,0,5A,0,5W,160MHz	7c*	Nec,Mic	BC327,BC638,BC638,BC840,++
2SA644				Nec	—
2SA645	Si-P	NF/S-L,70,0,8A,7W,>35MHz	13n	Mit	(BD386,BD418,BD526,BD830,++)
2SA646	Si-P	=2SA645: 90V	13n	Mit	(BD390,BD420,BD530,BD830,++)
2SA647	Si-P	=2SA645: 110V	13n	Mit	(BD390,BD420,BD530,BD830,++)
2SA648	Si-P	NF/S-L,120V,7A,60W,10MHz	23a	Nec	BD246D,2SB681,2SB895,2SB698,2SB816++
2SA649	Si-P	=2SA648: 150V	23a	Nec	BD246D,2SB681,2SB895,2SB698,2SBS16++
2SA65	Ge-P	S,16V,Ueb=12V,0,2A,6MHz,-/240ns	2a	Tos	ASY26..27,ASY48,ASY76..77

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2SA650	Si-P	NF/S-L, 150V, 10A, 100W, 10MHz	23a	Nec	BD246D, 2SA1386, 2SB681, 2SB817, 2SB908++
2SA651	Si-P	NF/S-L, 200V, 10A, 100W, 10MHz	23a	Nec	BD246F, 2SA1118, 2SA1294, 2SB800, 2SB645+
2SA652	Si-P	NF/S-L, 150/100V, 1A, 15W, 15MHz	22a	Nec	BD240D, 2SB608, 2SB628(A), 2SB881, 2SB991
2SA653	Si-P	=2SA852: 150/120V	22a	Nec	BD240D, 2SB608, 2SB628(A), 2SB681, 2SB991
2SA653A	Si-P	=2SA652: 150/140V	22a		BD240E, 2SB608, 2SB628(A), 2SB681, 2SB991
2SA654				Nec	—
2SA655				Nec	—
2SA656(A)	Si-P	NF/S-L, 130V, 7A, 50W, 5MHz	23a	Tos	BD246D, 2N6231, 2SB555, 2SB681, 2SB618++
2SA657(A)	Si-P	=2SA656: 100V	23a	Tos	BD318, BD248C, 2SB688, 2SB681, ++
2SA658(A)	Si-P	=2SA656: 70V	23a	Tos	BD316, BD248B, 2SB688, 2SB681, ++
2SA659(NP)	Si-P	Uni, 50V, 0,2A, 0,3W, 90MHz	7c	Say, Mic	BC212, BC257, BC307, BC557, ++
2SA66	Ge-P	S, 18V, Ueb=12V, 0,2A, 10MHz, -/225ns	2a	Tos	ASY26..27, ASY48, ASY78..77
2SA881	Si-P	Uni, 70V, 0,2A, 0,6W, 100MHz	9b	Tos	BC212, BC256, BC266, BC556, ++
2SA882				Tos	—
2SA663	Si-P	NF/S-L, 100V, 7A, 60W, 6MHz	23a	Tos	BD318, BD246C, 2N6229, 2SB775..778, ++
2SA666	Si-P	Uni, ra, 25V, 0,05A, 0,25W, 130MHz	7c	Mat, Mic	BC214, BC259, BC309, BC559, ++
2SA688A	Si-P	=2SA666: 45V	7c		BC214, BC418, BC560, 2SA1138..37, ++
2SA668	Si-P	S/Vid, 100V, 0,1A, 0,15W, 100MHz	7b	Mit	BF398, BF435..437, BSS88, 2SA1370, ++
2SA669	Si-P	S/Vid, 160V, 0,1A, 0,15W, 100MHz	7b	Mit	BF398, BF435..437, 2SA1370..1372, ++
2SA67	Ge-P	S, 18V, Ueb=12V, 0,2A, 14MHz	2a	Tos	ASY26..27, ASY48, ASY78..77
2SA870	Si-P	NF/S-L, 50V, 3A, 25W, 32MHz	17j	Hit, Mic	BD242, BD536, BD938, 2SA1288, ++
2SA671(K)	Si-P	NF/S-L, 50V, 3A, 25W, 32MHz	17j	Hit	BD242, BD536, BD938, 2SA1288, ++
2SA672	Si-P	Uni, ra, 50V, 0,2A, 0,2W, 80MHz	9b	Hit	BC214, BC416, BC560, 2SA1138..37, ++
2SA673	Si-P	Uni, 35V, 0,5A, 0,4W, 50MHz	9b, 7c	Hit	BC327..328, BC838, 2SA1515, 2SB910, ++
2SA873A(AK)	Si-P	=2SA673: 50V	9b, 7c	Hit	BC327, BC636, 2SA1883, 2SB910, ++
2SA674				Hit	—
2SA675	Si-P	Uni, 8V, 0,1A, 0,25W, 170MHz	7c	Nec, Mic	BC556, 2SA970, 2SA1049, 2SA1136
2SA676				Nec	—
2SA677	Si-P	Uni, 25V, 0,2A, 0,32W, 140MHz	10b	Son	BC213, BC256, BC308, BC558, ++
2SA678	Si-P	=2SA677: 50V	10b	Son	BC212, BC257, BC307, BC557, ++
2SA679	Si-P	NF/S-L, 120V, 12A, 100W, 6MHz	23a	Tos	BD746D, 2N6030..6031, 2SB555..556, ++
2SA68	Ge-P	AM, 20V, 10mA, 70MHz	1g	Mat	AF124..125, AF200, 2SA218..227
2SA680	Si-P	=2SA679: 100V	23a		BD746C, 2N6029..6031, 2SB555..556, ++
2SA881	Si-P	NF/S-L, 100V, 1A, 50MHz	14h	Tos	BD140, BD231, BD380, 2SB674..875, ++
2SA682	Si-P	NF/S-L, 60V, 0,75A, 5W, 100MHz	14h	Tos	BD140, BD231, BD380, 2SA1184, ++
2SA683(NC)	Si-P	Uni, 30V, 1A, 1W, 200MHz	7c(9mm)	Mat	2SA988, 2SB978, 2SB927, 2SB1312, ++
2SA664(NC)	Si-P	=2SA683: 60V	7c(9mm)	Mat	2SA1315, 2SB764, 2SB892, 2SB1041
2SA685	Si-P	Nix, Uni, 150V, 0,05A, 0,3W, 100MHz	7c	Mat, Mic	BF398, BF423, BF435..437, 2SA1370, ++
2SA69	Ge-P	AM, 20V, 10mA, 70MHz	1g	Mat	AF124..125, AF200, 2SA218..227
2SA695	Si-P	Uni, 25V, 0,7A, 0,5W, 150MHz	7b	Mit	BC327..328, BC636, BC638, 2SB910, ++
2SA696	Si-P	Uni, 45V, 0,3A, 0,5W, 130MHz	7b	Mit	BC327, BC838, BC638, 2SB910, ++
2SA697	Si-P	=2SA696: 65V	7b	Mit	BC327A, BC636, BC640, 2SB647, ++
2SA696	Si-P	NF/S-L, 130V, 0,SA, 7W, <200/800ns	13n	Mit	(2SA1195)
2SA699	Si-P	NF/S-L, 40V, 2A, 10W, 150MHz	13j	Mat	2SA887, (BD508, BD516, BD526, ++)
2SA699A	Si-P	=2SA699: 50/40V	13j		2SA887, (BD516, BD526)
2SA70	Ge-P	AM/FM, 20V, 10mA, 70MHz	1g	Mat	AF124, AF200, AF108, AF306
2SA700	Si-P	NF/S-L, 35V, 1,5A, 8W, 11MHz	17j	Hit	BD240, BD242, BD536, BD936, ++
2SA701(NP)	Si-P	Uni, 30V, 0,05A, 0,1W, 80MHz	7c	Say	BC213, BC258, BC306, BC558, ++
2SA702(NP)	Si-P	=2SA701: 50V	7c	Say	BC212, BC257, BC307, BC557, ++
2SA703	Si-P	NF/S-L, 25V, 1,5A, 7W, 70MHz	13n	Mit	(BD430, BD508, BD516, BD840, ++)
2SA704	Si-P	Uni, 25V, 0,2A, 0,32W, 140MHz	10b	Son	BC213, BC258, BC306, BC556, ++
2SA705	Si-P	=2SA704: 50V	10b	Son	BC212, BC257, BC307, BC557, ++
2SA708	Si-P	Uni-L, 40V, 1A, 7,9W, 120MHz	13m	Son	BD418, BD508, BD518, BD528, ++
2SA706-2	Si-P	=2SA708: 60V	13m		BD418, BD518, BD526, BD530, ++
2SA706-3	Si-P	=2SA706: 80V	13m		BD418, BD520, BD528, BD530, ++
2SA706-4	Si-P	=2SA706: 100V	13m		BD420, BD530
2SA707	Si-P	Uni-Tr/E, 40V, 0,5A, 0,75W, 180MHz	7c*	Nec	BC327, BC838, 2SA1515, 2SB910, ++
2SA708	Si-P	Uni, 80V, 0,7A, 0,6W, 100MHz	2a	Nec, Mic	BC303, BCX80, 2N3634..37, 2SA606, ++
2SA708A	Si-P	=2SA708: 100V, 95MHz	2a		BCX60, BSS17, 2N3634..37, 2SA606, ++
2SA709	Si-P	HF/S, 60V, 0,2A, 0,3W, 280MHz	7a	Nec	BC212, BC256, BC288, BC556, ++
2SA71	Ge-P	FM, 20V, 10mA, 100MHz	1g	Mat	AF124, AF200, AF106, AF306
2SA710	Si-P	HF/S, 50V, 0,1A, 600MHz, <80/180ns	2a	Nec	BF516, BF606, BSW24, 2N3250A..51A, ++
2SA711	Si-P	=2SA710: 1000MHz, <70/170ns	2a	Nec	BF516, BF808, BSW24, 2N3250A..51A, ++
2SA712	Si-P	S, 150V, 0,5A, 0,75W, 110/350ns	2a	Nec	BFT19, BFT28, 2N3836..3837, 2N5415
2SA713(S)	Si-P-Darl	15V, 0,3A, 0,25W, 180MHz, B=20000	5e	Nec	BC518, BC876, 2SA790, 2SA830, ++
2SA713A(AS)	Si-P-Darl	=2SA713: 40V, B=30000	5e		BC518, BC676, 2SA790, 2SA630, ++

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2SA714	Si-P	NF/S-L, 150V, 7A, 60W, 8MHz	23a	Say	BD246D, 2SB681, 2SB695, 2SB696, 2SB616++
2SA714L	Si-P	=2SA714: 100V	23a		BD246C, 2SB681, 2SB695, 2SB696, 2SB616++
2SA715	Si-P	NF/S-L, 35V, 2,5A, 10W, 160MHz	14h	Hit	BD376, 2SA1217, 2SB1009, 2SB1217, ++
2SA716				Say	—
2SA717	Si-P	Uni, 60V, 1A, 0,6W, <60/160ns	2a	Nec	2N4030..4033, 2N4036..4037
2SA718	Si-P	Uni, 60V, 0,2A, 0,3W, 250MHz	2a	Nec	BC212, BC556, BSW24, 2N2906..2907, ++
2SA719(NC)	Si-P	Uni, 30V, 0,5A, 0,625W, 200MHz	7c	Mat, Mic	BC327..328, BC636, 2SA1515, 2SB910, ++
2SA72	Ge-P	RF/IF AMP, 15V, 50mA, 250MHz	2a	Tos	AF124..126, AF200, 2SA218..227
2SA720(NC)	Si-P	=2SA719: 60V	7c	Mat, Mic	BC327(A), BC638, 2SB647, 2SB910, ++
2SA720A	Si-P	=2SA719: 80V, 120MHz	7c		BC640, 2N5400, 2SA695, 2SB647, ++
2SA721	Si-P	Uni, ra, 35V, 0,05A, 0,15W, 250MHz	7c	Mat, Mic	BC214, BC259, BC309, BC559, ++
2SA722	Si-P	=2SA721: 55V	7c	Mat, Mic	BC214, BC416, BC560, 2SA1136..37, ++
2SA723	Si-P	Uni, 40V, 0,5A, 0,25W, 160MHz	7c	Nec, Mic	BC327, BC636, 2SA1515, 2SB910, ++
2SA724	Si-P	Uni, 35V, 0,05A, 0,25W, 300MHz	7c	Nec	BC213, BC258, BC306, BC559, ++
2SA724				Nec	—
2SA725	Si-P	Uni, ra, 35V, 0,1A, 0,2W, 100MHz	7b	Mit	BC214, BC259, BC309, BC559, ++
2SA726	Si-P	=2SA725: 50V	7b	Mit	BC214, BC416, BC560, 2SA1136..37, ++
2SA727				Mit	—
2SA728	Si-P	Uni, 30V, 0,1A, 0,1W, 100MHz	41c	Mit	BC213, BC258, BC308, BC559, ++
2SA726A	Si-P	=2SA726: 60V, 130/700ns	41c		BC212, BC558, BSW24, 2N2906..2907, ++
2SA73	Ge-P	RF/IF AMP, 20V, 10mA, 400MHz	4g	Tos	AF124..126, AF200, 2SA218..227
2SA730	Si-P	=2SA719: 0,6W	7c°	Mat, Mic	→2SA719
2SA731	Si-P	=2SA720: 0,6W	7c°	Mat, Mic	→2SA720
2SA732	Si-P	Uni, 40V, 0,3A, 0,65W, 200MHz	2a	Fui	BC160..161, BC303..304, 2N2303, ++
2SA733	Si-P	Uni, 60V, 0,1A, 0,25W, 180MHz	7c	Nec, Mic	BC212, BC257, BC307, BC557, ++
2SA734				Son	—
2SA735				Son	—
2SA736				Son	—
2SA737				Son	—
2SA738	Si-P	NF/S-L, 25V, 1,5A, 8W, 180MHz	14h	Hit	BD136, BD227, BD376, 2SB1009, ++
2SA739	Si-P	S-L, 400/400V, 3A, 50W	23a	Tos	BUW22..23, BUW32
2SA74	Ge-P	RF/IF AMP, 15V, 50mA, 250MHz	2a	Tos	AF121(S), AF202(S), AFY18
2SA740(A)	Si-P	NF/S-L, 150V, 1,5A, 25W, 8MHz	17j	Tos	BD240D, 2SA940, 2SB628(A), 2SB861, ++
2SA741(N)	Si-P	S, 20V, 0,1A, 0,36W, <70/120ns	2a	Hit	BSW24, 2N3209, 2N4034..35, 2N4125..28++
2SA742(N)	Si-P	S, 60V, 0,5A, 0,7W, <40/100ns	2a	Hit	2SA717
2SA743	Si-P	NF/S-L, 50V, 1A, 8W, 120MHz	14h	Hit	BD136, BD229, BD376, 2SB1007, ++
2SA743A	Si-P	=2SA743: 80V	14h		BD140, BD231, BD360, 2SB1007, ++
2SA744	Si-P	NF/S-L, 80V, 8A, 70W, 15MHz	23a	Sak	BD246B, BD314, 2N5872, 2SB681, ++
2SA745	Si-P	=2SA744: 100V	23a	Sak	BD246C, BD318, 2N6229, 2SB681, ++
2SA745A	Si-P	=2SA745: 120V	23a		BD246C, 2N6230..31, 2SB661, 2SB696, ++
2SA746	Si-P	NF/S-L, 60V, 10A, 100W, 15MHz	23a	Sak	BD246B, BD314, 2N5876, 2SB681, ++
2SA747	Si-P	=2SA746: 120V	23a	Sak	BD246C, 2N6230..31, 2SB681, 2SB696, ++-
2SA747A	Si-P	=2SA747: 140V	23a		BD246D, 2N6231, 2SA806, 2SB681, 2SB696+-
2SA748	Si-P	NF/S-L, 70V, 2A, 15W, 120MHz	17j	Mat	2SA1078, 2SA1296
2SA749	Si-P	Nix, S, 100V, 0,05A, 0,25A, >40MHz	7c	Mat, Mic	BF396, BF423, 2SA1017, 2SB715..716, ++
2SA749A	Si-P	=2SA749: 130V	7c		BF398, BF423, 2SA1019, 2SB716A, ++
2SA75	Ge-P	RF/IF AMP, 15V, 50mA, 250MHz	2a	Tos	AF121(S), AF202(S), AFY18
2SA750	Si-P	Uni, ra, 50V, 0,05A, 0,25W, 100MHz	7c	Nec	BC214, BC416, BC560, 2SA1136..37, ++
2SA751	Si-P	Uni, 30V, 1A, 1W, 200MHz	7c°	Mat	BC327..328, BC636, 2SB809, 2SB1116, ++
2SA752	Si-P	=2SA751: 60V	7c°	Mat	BC327A, BC638, 2SB647, 2SB734, ++
2SA753	Si-P	NF/S-L, 140V, 10A, 100W, 20MHz	23a	Hit	BDX20, 2SB681, 2SB697, 2SB617, ++
2SA754	Si-P	NF/S-L, 50V, 2A, 20W, 50MHz	17j	Hit	BD240, 2SA746, 2SA1078, 2SA1288, ++
2SA755	Si-P	=2SA754	17j	Hit	BD240, 2SA748, 2SA1076, 2SA1288, ++
2SA756	Si-P	NF/S-L, 100V, 8A, 50W, 20MHz	2SA	Hit	BD246C, BDX96, 2N6229..31, 2SB681, ++
2SA757	Si-P	NF/S-L, 120V, 7A, 60W, 24MHz	2SA	Hit	BD246C, BDX20, 2N6230..31, 2SB681, ++
2SA758	Si-P	NF/S-L, 130V, 7A, 60W, 20MHz	2SA	Hit	BDX20, 2N6231, 2SA982, 2SB681, ++
2SA759	Si-P	SMD, Uni, 60V, 0,2A, 200MHz	35a	Nec	BC856, BCW68, BCW89, 2SA1620, ++
2SA78	Ge-P	RF/IF AMP, 15V, 50mA, 250MHz	2a	Tos	AF124..125, AF106, AF308, 2SA340..342
2SA760	Si-P	SMD, Uni, 50V, 0,03A, 100MHz	35a	Nec	BC858..857, BCW69..370, BCW69, ++
2SA761(S)-1	Si-P	Uni, 110V, 2A, 6,3W(Tc=25°), 60MHz	2a	Son	BCX60, BSS17, 2N5322
2SA761(S)-2	Si-P	=2SA761-1: 140V	2a		(BUY90)
2SA762-1	Si-P	=2SA761-1: 23W	22a	Son	2SA1078..1079
2SA762-2	Si-P	=2SA761-1: 140V, 23W	22a		2SA1079
2SA763	Si-P	Uni, ra, 30V, 0,05A, 0,2W, 120MHz	7c	Njr	BC214, BC259, BC309, BC559, ++
2SA764	Si-P	NF/S-L, 60V, 8A, 40W, 10MHz	22a	Sak	BD244A, BD544A, BD796, 2N6317..18, ++
2SA765	Si-P	=2SA764: 60V	22a	Sak	BD244B, BD544B, BD800, 2N6318, ++

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2SA766(S)	Si-P	NF/S-L, 150V, 0,4A, 20W(Tc=80°), 15MHz	22a	Mat	2SA839, 2SA940, 2SB628(A), 2SB861, ++
2SA767	Si-P	Uni, 55V, 0.1A, 0,2W, 150MHz	2a	Tos	BC212, BC257, BC307, BC557, ++
2SA768	Si-P	NF/S-L, 60V, 4A, 30W, 10MHz	17j	Sak	BD244A, BD536, 2SB882, 2SB690, ++
2SA769	Si-P	=2SA768: 80V	17j	Sak	BD244B, BD538, 2SB882, 2SB890, ++
2SA77	Ge-P	RF/IF AMP, 15V, 50mA, 250MHz	2a	Tos	AF124..125, AF106, AF306, 2SA340..342
2SA770	Si-P	NF/S-L, 60V, 6A, 40W, 20MHz	17j	Sak	BD244A, BD798, BD808, 2SB633, ++
2SA771	Si-P	=2SA770: 80V	17j	Sak	BD244B, BD800, BD810, 2SB633, ++
2SA772(-1,-2)	Si-P	Uni, 20V, 2A, 0,75W, 80MHz	7c(9mm)	Son	2SA1382, 2SB736..739, 2SB692, 2SB1312, ++
2SA773(-1,-2)	Si-P	Uni, 80..70V, 1A, 0,75W, 65MHz	7c(9mm)	Son	2SA1362, 2SB892, 2SA1315, 2SB847, ++
2SA774	Si-P	Uni, 35V, 0,05A, 0,15W, 120MHz	≈2a	Mat	BC213, BC258, BC308, BC558, ++
2SA774A	Si-P	=2SA774: 55V	≈2a		BC212, BC257, BC307, BC557, ++
2SA775	Si-P	NF/S-L, TV-VA, 100V, 0,7A, 12,5W, 30MHz	17j	Hit	2SA985(A), 2SA1078, 2SB861
2SA775A	Si-P	=2SA775: 120V	17j		2SA985(A), 2SA1078, 2SB861
2SA776(A)	Si-P	Uni, ra, 55V, 0,05A, 0,2W, 180MHz	2a	Tos	BC214, BC416, BC560, 2SA1136..37, ++
2SA777(NC)	Si-P	Uni, 80V, 0,5A, 1W, 120MHz	7c(9mm)	Mat	2SA1533, 2SB987, 2SB1041, 2SB1297, ++
2SA778	Si-P	S/Vid, 150V, 0,05A, 0,2W, 80MHz	9b, 7c	Hit	BF398, BF423, BF435..437, 2SA1370, ++
2SA778A(AK)	Si-P	=2SA778: 180V	9b, 7c		BF423, BF435..437, 2SA1370
2SA779(K)	Si-P	NF/S-L, 35V, 1,5A, 10W, 110MHz	≈17j	Hit	2SA699, 2SA748, 2SA887, 2SA1288, ++
2SA78	Ge-P	S, 40V, 0,4A, 40MHz, -/335ns	49	Tos	ASY76..77
2SA780(K)	Si-P	NF/S-L, 50V, 1A, 10W, 120MHz	≈17j	Hit	2SA748, 2SA887, 2SA1078, 2SA1288, ++
2SA780A	Si-P	=2SA780: 80V	≈17j		2SA985(A), 2SA1078, 2SA1195, 2SA1288, ++
2SA781	Si-P	S, 20V, 0,2A, 0,2W, <80/160ns	9b	Hit	BSW24, 2N3209, 2N3250..51, 2SA1458, ++
2SA781K	Si-P	=2SA781: 550MHz, <70/120ns	7c		BSW24, 2N3209, 2N3250..51, 2SA1458, ++
2SA782	Si-P	Uni, 80V, 0,03A, 0,15W, 200MHz	9c	Rhm	BC556, 2SA893(A), 2SB715..716(A), ++
2SA783	Si-P	=2SA782: 50V	9c	Rhm	BC212, BC257, BC307, BC557, ++
2SA784	Si-P	=2SA782: 25V	9c	Rhm	BC213, BC256, BC308, BC558, ++
2SA785	Si-P	Uni, 80V, 0,05A, 0,15W, 180MHz	9c	Rhm	BC556, 2SA893(A), 2SB715..716(A), ++
2SA786	Si-P	=2SA785: 50V	9c	Rhm	BC212, BC257, BC307, BC557, ++
2SA787	Si-P	=2SA785: 25V	9c	Rhm	BC213, BC258, BC308, BC558, ++
2SA786	Si-P	Uni, ra, 50V, 0,03A, 0,15W, 200MHz	9c	Rhm	BC214, BC416, BC560, 2SA1136..37, ++
2SA789	Si-P	=2SA768: 25V	9c		BC214, BC259, BC309, BC559, ++
2SA79	Ge-P	S, 20V, Ueb=12V, 0,2A, >4MHz	2a	Tos	ASY26..27, ASY48, ASY76..77
2SA790(M)	Si-P-Darl	Uni, 30V, 0,3A, 0,3W, B>1000	5e	Rhm	BC516, MPS-A75..77, 2SA1555, 2SB1076, ++
2SA791	Si-P-Darl	=2SA790: 25V	9c	Rhm	BC516, BC876, MPS-A75..77, 2SB1076, ++
2SA792				Fui	—
2SA793	Si-P	Uni, 80V, 0,6A, 0,8W, 100MHz	2a	Fui	BC303, BSV17, 2N3634..37, 2SA606, ++
2SA794	Si-P	NF/S-L, 100V, 0,5A, 5W, 120MHz	14h	Mat	BD140, BD231, BD360, 2SB874..875
2SA794A	Si-P	=2SA794: 120V	14h		2SA1178, 2SA1184, 2SA1220(A), 2SA1358
2SA795	Si-P	NF/S-L, 150V, 0,25A, 10W, 120MHz	14h	Mat	2SA1178, 2SA1220A
2SA795A	Si-P	=2SA795: 180V, 1A	14h		2SA1249, 2SB649
2SA798	Si-P-Darl	S, 30V, 0,3A, 0,3W, B=40000	7c	Njr	BC516, BC876, MPS-A75..77, 2SB1076, ++
2SA797	Si-P	HF, 90V, 0,05A, 0,15W, 100MHz	2a	Mit	BF397..398, BF423, BSS68, 2SA893, ++
2SA798	Si-P	Dual, ra, 50V, 0,1A, 0,4W, 100MHz	5-SIP	Mit	—
2SA799(F)	Si-P	S, 60V, 1,5A, 1W, <45/110ns	2a	Fui	2N3720
2SA60	Ge-P	RF/IF AMP, 15V, 50mA, 250MHz	2a	Hit	AF124..126, AF200, 2SA218..227
2SA800	Si-P	UHF-A, 20V, 0,03A, 2,5GHz	5g	Nec	BFQ78, BFR99, 2SA967, 2SA1058
2SA801	Si-P	UHF-A, 20V, 0,05A, 4GHz	5ts	Nec	BFQ32, 2SA1057, 2SA1223
2SA802	Si-P	Nix, S, 130V, 0,03A, 0,15W, 50MHz	9c	Rhm	BF398, BF423, BF435..437, 2SA1370, ++
2SA803	Si-P	=2SA802: 200MHz	9c	Rhm	BF398, BF423, BF435..437, 2SA1370, ++
2SA804	Si-P	=2SA602: 180MHz	9c	Rhm	BF398, BF423, BF435..437, 2SA1370, ++
2SA805	Si-P	=2SA602: 180V	9c	Rhm	BF423, BF436..437, 2SA1370..1371, ++
2SA806	Si-P	=2SA802: 210V	9c	Rhm	BF423, BF436..437, 2SA1370..1371, ++
2SA807	Si-P	NF/S-L, 60V, 6A, 50W, 10MHz	23a	Sak	BD246A, BD312, BDX92, 2N5871..72, ++
2SA808	Si-P	=2SA607: 80V	23A	Sak	BD246B, BD314, BDX94, 2N5872, ++
2SA808A	Si-P	=2SA808: 100V	23A		BD246C, BD318, BDX96, 2N6229..30, ++
2SA809	Si-P	S/Vid, 150/120V, 0,05A, 0,7W, 100MHz	2a°	Fui	(BF470, BF818, BF870, 2SA1406..07, ++)
2SA81	Ge-P	RF/IF AMP, 20V, 10mA, 400MHz	4g	Hit	AF124..126, AF200, 2SA218..227
2SA810	Si-P	=2SA809: 150/150V	2a°	Fui	(BF470, BF818, BF870, 2SA1406..07, ++)
2SA811	Si-P	SMD, Uni, 50V, 0,03A, 100MHz	35a	Nec	BC856..857, BCW69..70, BCW89, ++
2SA811A	Si-P	=2SA811: 120V, 90MHz	35a		2SA1312, 2SA1566
2SA812	Si-P	SMD, Uni, 80V, 0,1A, 180MHz	35a	Nec	BC858, BCW89, 2SA1311
2SA613	Si-P	SMD, Uni, 60V, 0,2A, 200MHz	35a	Nec	BCW88, 2SA1620
2SA814	Si-P	NF/S-L, 120V, 1A, 15W, 30MHz	17j	Tos	BD942, 2SA839, 2SA940, 2SB536..537, ++
2SA815	Si-P	=2SA814: 100V	17j	Tos	BD240C, BD242C, BD940, 2SB536..537, ++
2SA818	Si-P	NF/S-L, 80V, 0,75A, 10W, 100MHz	17j	Tos, Mic	BD240B, BD242B, BD938, 2SB536..537, ++
2SA817	Si-P	Uni, 80V, 0,3A, 0,6W, 100MHz	7c	Tos, Mic	BC840, 2N5400..01, 2SA1683, 2SB910, ++

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2SA817A	Si-P	=2SA817: 0,4A, 0,8W	7c(9mm)		BC640, 2N5400..01, 2SA965, 2SA1533, ++
2SA818	Si-P	Vid, 180V, 0,05A, 120MHz	13m	Tos	BF483..465, MPS-U60, 2SA964(A), ++
2SA819	Si-P	Uni, 40V, 0,3A, 0,3W, 240MHz	7c	Rhm	BC327, BC636, 2SA1515, 2SA1683, ++
2SA82	Ge-P	RF/IF AMP, 15V, 50mA, 250MHz	2a	Hit	AF124..12S, AF200, 2SA218..227
2SA820	Si-P	=2SA805	7c	Rhm	→2SA805
2SA821	Si-P	=2SA806	7c	Rhm	→2SA806
2SA822	Si-P	Uni, 80V, 0,03A, 0,25W, 200MHz	7c	Rhm	BC556, 2SA893(A), 2SB715..716(A), ++
2SA823	Si-P	=2SA822: 50V	7c	Rhm	BC212, BC257, BC307, BC557, ++
2SA824	Si-P	=2SA822: 30V	7c	Rhm	BC213, BC258, BC308, BC558, ++
2SA825(S)	Si-P	=2SA785: S: Fig. 41c	7c,41c	Rhm	→2SA785
2SA82S	Si-P	=2SA786:	7c	Rhm	→2SA786
2SA827	Si-P	Uni, 25V, 0,05A, 0,25W, 180MHz	7c	Rhm	BC213, BC258, BC308, BC558, ++
2SA828	Si-P	Uni, ra, 50V, 0,03A, 0,25W, 180MHz	7c	Rhm	BC214, BC416, BC560, 2SA1136..37, ++
2SA829	Si-P	=2SA828: 25V	7c	Rhm	BC214, BC259, BC309, BC559, 2SA1137+
2SA83	Ge-P	RF/IF AMP, 15V, 50mA, 250MHz	2a	Hit	AF124..127, AF200, 2SA218..227
2SA830(S)	Si-P-Darl	=2SA790: S: Fig41c	5c(B)	Rhm	→2SA790
2SA831	Si-P-Darl	=2SA791	7c	Rhm	→2SA791
2SA832	Si-P	=2SA802:	7c	Rhm	→2SA802
2SA833	Si-P	Uni, 130V, 0,03A, 0,25W, 200MHz	7c	Rhm	BF398, BF423, 2SA1019, 2SB716A, ++
2SA834	Si-P	=2SA833: 0,05A	7c	Rhm	BF398, BF423, 2SA1019, 2SB716A, ++
2SA835	Si-P	S/Vid-L, 140V, 0,5A, 7,9W	13m	Son	BF463..465, MPS-U60, 2SA964(A), ++
2SA836	Si-P	Uni, ra, 55V, 0,1A, 0,2W, 200MHz	9b,7c	Hit	BC214, BC418, BC560, 2SA1136..37, ++
2SA837	Si-P	NF/S-L, 90V, 4A, 50W(Tc=75°), 10MHz	23A	Mat	BD246C, BD314, BDX96, 2N6228..27, ++
2SA838	Si-P	Uni, 30V, 0,03A, 0,25W, 300MHz	7c	Mat	BC308, BC556, BF324, BF450..451, ++
2SA839	Si-P	NF/S-L, 150V, 1,5A, 25W, 6MHz	17j	Tos	BD240D, 2SA940, 2SB608, 2SB628(A), 2SB681
2SA84	Ge-P	RF/IF AMP, 20V, 10mA, 400MHz	4g	Hit	AF124..126, AF200, 2SA218..227
2SA840	Si-P	Vid, 140V, 0,5A, 0,75W, 45MHz	7c(9mm)	Son	BF491..493, BF423A, MPS-A92..93, ++
2SA841	Si-P	NF, ra, 80V, 0,05A, 0,2W, 140MHz	7c	Tos	BC214, BC416, BC560, 2SA1136..37, ++
2SA842	Si-P	=2SA841: 40V	7c	Tos	BC214, BC416, BC560, 2SA1136..37, ++
2SA843	Si-P	TV-VA-E, 200V, 0,5A, 20W, 35MHz	17j	Mat	BD240F, 2SA968B, 2SA1133, 2SB861
2SA844	Si-P	Uni, 55V, 0,1A, 0,3W, 200MHz	9b,7c	Hit	BC212, BC257, BC307, BC556, ++
2SA845	Si-P	Vid, 150V, 0,05A, 0,2W, >40MHz	2a	Hit	BF398, BF423, BF435..437, 2SA1370, ++
2SA845A	Si-P	=2SA845: 180V	2a		BF423, BF436..437, 2SA1370..71, ++
2SA846				Hit	—
2SA847	Si-P	Uni, ra, 90V, 0,05A, 0,2W, 150MHz	7b	Mit	2SA872(A), 2SA941..942, 2SA970, ++
2SA847A	Si-P	=2SA847: 120V	7b		2SA872A, 2SA941, 2SA970, 2SA1018, ++
2SA848	Si-P	Vid, 150/120V, 0,05A, 1W, 100MHz	2a*	Fui	(BF470, BF818, BF870, 2SA1406..07, ++)
2SA849	Si-P	=2SA848: 150/150V	2a*	Fui	(BF470, BF818, BF870, 2SA1406..07, ++)
2SA85	Ge-P	RF/IF AMP, 15V, 50mA, 250MHz	2a	Hit	AF124..126, AF200, 2SA218..227
2SA850	Si-P	Uni, 100V, 0,5A, 0,8W, 130MHz	7b	Mit	BC640, 2SA1706, 2SB647, 2SB984, ++
2SA851	Si-P	Uni, 50V, 0,1A, 0,3W, 150MHz	7a	Mit	BC212, BC257, BC307, BC557, ++
2SA852	Si-P	=2SA852: 35V	7a	Mot	BC213, BC258, BC308, BC558, ++
2SA853	Si-P	=2SA852: 35V, ra	7a	Mit	BC214, BC259, BC309, BC559, 2SA970++
2SA854(S)	Si-P	Uni, 40V, 0,5A, 0,4W, 200MHz	7c,41c	Rhm	BC327, BC636, BC638, 2SA1515, ++
2SA855	Si-P	Uni, 80V, 0,05A, 0,15W, 140MHz	2a	Tos	BC212, BC256, BC286, BC558, ++
2SA856(A)	Si-P	=2SA855: 50V, ra	2a	Tos	BC214, BC418, BC560, 2SA1136..37, ++
2SA857	Si-P	Vid, 150/120V, 0,05A, 0,5W, 100MHz	7c	Fui	BF398, BF423, BF435..437, 2SA1370, ++
2SA858	Si-P	=2SA857: 150/150V	7c	Fui	BF398, BF423, BF435..437, 2SA1370, ++
2SA859	Si-P	=MPS-A92	7e	Mot	→MPS-A92
2SA86	Ge-P	HF, 45V, 50mA, 35MHz	4g*	Hit	AF121(S), AF202(S), AFY18
2SA860	Si-P	=MPS-A93	7a	Mot	→MPS-A93
2SA861	Si-P	NF/S-L, 20V, 2A, 80MHz	13j	Son	2SA473, 2SA699, 2SA748, 2SA887, ++
2SA866	Si-P	Uni, 30V, 0,1A, 0,3W, 150MHz	7e	Njr	BC213, BC258, BC308, BC558, ++
2SA867	Si-P	=2SA866: 80V	7e	Njr	BC212, BC256, BC268, BC558, ++
2SA868	Si-P	=2SA866: 90V	7e	Njr	2SA970, 2SA1136..1137, 2SA1285(A), ++
2SA869	Si-P	Uni, 30V, 0,4A, 0,5W, 150MHz	7e	Njr	BC327..328, BC636, 2SA1515, 2SB910, ++
2SA87	Ge-P	RF/IF AMP, 15V, 50mA, 250MHz	2a	Hit	AF124, AF106, AF306, 2SA340..342
2SA870	Si-P	=2SA869: 60V	7e	Njr	BC327, BC638, 2SA1683, 2SB910, ++
2SA871	Si-P	Uni, ra, 30V, 0,05A, 0,2W, 120MHz	7e	Njr	BC214, BC259, BC309, BC559, 2SA970++
2SA872	Si-P	Uni, ra, 90V, 0,05A, 0,3W, 120MHz	7c	Hit	2SA941..942, 2SA970, 2SA1018, 2SA1038, ++
2SA872A	Si-P	=2SA872: 120V	7c		2SA941, 2SA970, 2SA1016, 2SA1038, ++
2SA873	Si-P	Uni, 60V, 0,2A, 0,3W, 220MHz	7a	Fui	BC212, BC256, BC268, BC558, ++
2SA874(M)	Si-P	=2SA854: 0,3W	9c	Rhm	→2SA954
2SA875				Nec	—
2SA876(H)	Si-P	Uni, 70V, 0,5A, 0,35W, 200MHz	2a	Hit	BC640, BCX39, 2N5400..01, 2SB649, ++
2SA877	Si-P	NF/S-L, 80V, 10A, 100W, 15MHz	2SA	Sak	BD246B, BD314, 2N5876, 2SB555..556, ++

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2SA878	Si-P	=2SA877: 120V	2SA	Sak	BD246C, 2N6230..31, 2SB555..56, 2SB681++
2SA879	Si-P	Vid, 250/200V, 0,07A, 1W, 80MHz	7c(9mm)	Mat	BF436..437, BF423A, 2SA1371, ++
2SA88	Ge-P	RF/IF AMP, 20V, 10mA, 400MHz	4g	Hit	AF124..125, AF106, AF306, 2SA340..342
2SA880	Si-P	Uni, ra, 35V, 0,05A, 0,15W, 120MHz	9c	Mat	BC214, BC259, BC309, BC559, 2SA870++
2SA881	Si-P	Uni, 40V, 1A, 0,6W, 150MHz	9c	Rhm	BC636, BC638, 2SA647, 2SB1118, ++
2SA882	Si-P	NF/S-L, 130V, 7A, 100W, 7MHz	2SA	Mat	BD246D, 2SA982, 2SB681, 2SB695, 2SB696++
2SA883	Si-P	Uni, 60V, 0,2A, 0,3W, 280MHz	7c	Nip	BC212, BC256, BC288, BC556, ++
2SA884	Si-P	Dual, 65V, 0,2A, 0,27W, 140MHz	6-DIP	Son	—
2SA885	Si-P	NF/S-L, 45V, 1A, 5W, 200MHz	14h	Mat	BD136, BD227, BD376, 2SB1007, ++
2SA886	Si-P	NF/S-L, 50V, 1,5A, 5W, 150MHz	14h	Mat	BD136, BD229, BD376, 2SB744(A), ++
2SA887	Si-P	NF/S-L, 70V, 2A, 10W, 150MHz	13j	Mat	(2SA748, 2SA1078, 2SA1288)
2SA888	Si-P	Uni, 25V, 0,05A, 0,35W, 100MHz	7e	Mat, Mic	BC213, BC256, BC308, BC559, ++
2SA889	Si-P	=2SA888: 45V	7e	Mat, Mic	BC212, BC257, BC307, BC557, ++
2SA89	Ge-P	RF/IF AMP, 20V, 10mA, 400MHz	4g	Hit	AF124..125, AF106, AF306, 2SA340..342
2SA890	Si-P	Uni, 30V, 0,5A, 0,625W, 200MHz	7e	Mat, Mic	BC327..328, BC638, 2SA1515, 2SB910, ++
2SA891	Si-P	=2SA890: 60V	7e	Mat, Mic	BC327A, BC638, BC640, 2SB647, ++
2SA892	Si-P-Darl	S-L, 100V, 6A, 40W, B>300	17c	Sak	BD644, BD896, BDW24, BDW84, 2SB1339+
2SA893	Si-N	Uni, ra, 90V, 0,05A, 0,3W, 120MHz	7c	Hit	2SA941..942, 2SA970, 2SA1016, 2SA1038, ++
2SA893A	Si-P	=2SA893: 120V	7c		2SA941, 2SA970, 2SA1016, 2SA1038, ++
2SA894	Si-P	Uni, 30V, 1A, 0,6W, 150MHz	7c	Njr	BC638, BC638, 2SB647, 2SB909, ++
2SA895	Si-P	VHF, 30V, 30mA, 500MHz	7c	Njr	BF324, BF414, BF506, BF914, BF936++
2SA896(-1,-2)	Si-P	Vid, 200V, 0,1A, 0,75W, 70MHz	7c(9mm)	Son	BF436..437, BF423A, 2SA1370..71, ++
2SA897	Si-P	NF/S-L, 60V, 2A, 0,95W, 55MHz	13j	Son	2SA746, 2SA887, 2SA1078, 2SA1288, ++
2SA898	Si-P	Vid-L, 150/120V, 0,05A, 100MHz	14h	Fui	BF470, BF472, BF416, BF418, ++
2SA899	Si-P	=2SA898: 150/150V	14h	Fui	BF470, BF472, BF416, BF418
2SA90	Ge-P	HF, 30V, 20mA, >60MHz	4g°	Hit	AF124..128, AF106, AF306, 2SA340..342
2SA900	Si-P	NF/S-L, 20V, 1A, 4W, 200MHz	14h	Mat	BD136, BD227, BD376, 2SB1009, ++
2SA901	Si-P	Uni, 40V, 0,1A, 0,2W, 100MHz	7b	Mit	BC213, BC257, BC307, BC557, ++
2SA902	Si-P	=2SA903: ra	7c	Mit	BC214, BC416, BC560, 2SA1136..37, ++
2SA903	Si-P	Uni, 50V, 0,1A, 0,2W, 150MHz	7c	Mit	BC212, BC257, BC307, BC557, ++
2SA904	Si-P	Uni, 90V, 0,05A, 0,2W, 150MHz	7b	Mit	2SA893(A), 2SA970, 2SB715..716(A), ++
2SA904A	Si-P	=2SA904: 120V	7b		2SA893A, 2SA970, 2SA1017, 2SB716(A), ++
2SA905	Si-P	Vid, 120V, 0,05A, 0,8W, 200MHz	7b	Mit	BF398, 2SA893A, 2SA970, 2SA1017, ++
2SA906	Si-P	Uni, ra, 40V, 0,1A, 0,2W, 100MHz	7b	Mit	BC214, BC418, BC560, 2SA1136..37, ++
2SA907	Si-P	NF/S-L, 100V, 15A, 150W, 10MHz	2SA	Sak	BD318, MJ2955, 2N6029..6031, ++
2SA908	Si-P	=2SA907: 150V	2SA	Sak	MJ15016, 2N6609, 2SA1147, 2SB645, ++
2SA909	Si-P	=2SA907: 200V	2SA	Sak	MJ15016, 2SA1116..1117, 2SB552, 2SB645+
2SA910				Fui	—
2SA911	Si-P	S, 850/550V, 0,1A, 0,47W, 9MHz	2a	Son	—
2SA912(NC)	Si-P	NF, ra, 150V, 0,05A, 0,75W, 200MHz	7c(9mm)	Mat	2SA1016K, 2SA1123..1124, 2SA1462
2SA913	Si-P	NF/S-L, 150V, 1A, 15W, 120MHz	17j	Mat	2SA968(A,B), 2SA1111..1112, 2SB628(A), ++
2SA913A	Si-P	=2SA913: 180V	17j		2SA968A,B, 2SA1011, 2SA1112, 2SB628A
2SA914	Si-P	NF, 150V, 0,05A, 200MHz	14h	Mat	BF470, BF472, BF416, BF418, ++
2SA915	Si-P	NF, 120V, 0,05A, 1W, 80MHz	9b	Nec	2SA1016..17, 2SA1123..24, 2SB1348, ++
2SA916	Si-P	=2SA915: 160V	9b	Nec	2SA1123..24, 2SA1281, 2SB1348
2SA917	Si-P	Vid, 120V, 0,1A, 0,75W, 70MHz	7c(9mm)	Son	BF398, 2SA970, 2SA1136, 2SA1285(A), ++
2SA918	Si-P	Uni, 40V, 0,3A, 0,3W, 200MHz	7a	Fui	BC327, BC638, 2SA1515, 2SA1883, ++
2SA919	Si-P	S-L, 850V, 0,1A, 0,95W, 9MHz	13m	Son	—
2SA92	Ge-P	RF/IF AMP, 15V, 50mA, 250MHz	2a	Tos	AF124..128, AF200, 2SA218..227
2SA920	Si-P	NF/S-L, 200V, 0,5A, 7,9W, 40MHz	13m	Son	BF463..464, MPS-U60
2SA921	Si-P	Uni, ra, 120V, 0,02A, 0,25W, 200MHz	7c	Mat	2SA941, 2SA970, 2SA1016, 2SA1038, ++
2SA922(-1,-2)	Si-P	NF-Tr/E, 80..100V, 1A, 0,625W, 120MHz	2a	Son	BCX60, BSS17, BSW40, 2N3834..37, ++
2SA923(-1,-2)	Si-P	S/Vid, 200V, 0,2A, 0,625W, 70MHz	2a	Son	BFQ38..37, (BF616, BF618, MPS-U60, ++)
2SA924	Si-P	Uni, 30V, 0,1A, 0,5W, 120MHz	7a	Hit	BC213, BC258, BC308, BC556, ++
2SA925(-1,-2)	Si-P	VHF/S, 30..45V, 30mA, 0,25W, 500MHz	7c	Son	BF324, BF414, BF506, BF914, BF936++
2SA926				Nec	—
2SA927	Si-P	Uni, 60V, 0,25A, 0,5W, 290MHz	7c	Fui	BC212, BC256, BC288, BC556, ++
2SA928	Si-P	HF, 20V, 1A, 0,25W	7c	Son	—
2SA929	Si-P	Uni, ra, 55V, 0,05A, 0,2W, 80MHz	7c	Say	BC418, BC560, 2SA970, 2SA1136..37, ++
2SA93	Ge-P	RF/IF AMP, 15V, 50mA, 250MHz	2a	Tos	AF124..128, AF200, 2SA218..227
2SA930	Si-P	=2SA929: 40V	7c	Say	BC214, BC416, BC560, 2SA1136..37, ++
2SA931	Si-P	Vid, 150/120V, 0,05A, 0,45W, >70MHz	2a	Fui	BF398, BF423, BF435..437, 2SA1370, ++
2SA932	Si-P	=2SA931: 150/150V	2a	Fui	BF388, BF423, BF435..437, 2SA1370, ++
2SA933(A,S,AS)	Si-P	Uni, 50(A=60)V, 0,1A, 0,3W, 140MHz	7c, 41c	Rhm	BC212, BC256, BC307, BC557, ++
2SA933(S)LN	Si-P	=2SA933: ra	7c, 41c		BC416, BC560, 2SA1039, 2SA1137, ++
2SA934	Si-P	Uni, 40V, 1A, 0,75W, 150MHz	7c(9mm)	Rhm	BC327, 2SA1287, 2SB978, 2SB1041, ++

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2SA935	Si-P	=2SA934: 80V, 0,7A	7c(9mm)	Rhm	BC640, 2SA965, 2SB647, 2SB1041, ++
2SA936	Si-P-Darl	Uni, 40V, 0,3A, 0,3W, B>10000	5e	Rhm	BC516, BC876, MPS-A75..77, 2SB1078, ++
2SA937(M)	Si-P	=2SA933:	9c	Rhm	→2SA933
2SA937LN,MLN	Si-P	=2SA933: ra	9c	Rhm	→2SA933LN
2SA938	Si-P	Uni, 50V, 0,5A, 0,5W	7c	Son	BC327, BC638, 2SA1683, 2SB647, ++
2SA939	Si-P	Vid, 250V, 0,05A, 130MHz	14h	Fui	BF470, BF472, BF416, BF418, ++
2SA94	Ge-P	RF/IF AMP, 15V, 50mA, 250MHz	2a	Hit	AF124..127, AF200, 2SA218..227
2SA940	Si-P	TV-VA, NF/S-L, 150V, 1,5A, 25W, 4MHz	17j	Tos	2SA939, 2SB608, 2SB628(A), 2SB861
2SA941	Si-P	Uni, ra, 120V, 0,05A, 0,3W, 150MHz	7c	Tos	2SA972A, 2SA992, 2SA1016, 2SA1039, ++
2SA942	Si-P	=2SA941: 90V	7c	Tos	2SA872(A), 2SA992, 2SA1016, 2SA1038, ++
2SA943				Nec	—
2SA944				Nec	—
2SA945				Nec	—
2SA946				Fui	—
2SA947				Tos	—
2SA948				Tos	—
2SA949	Si-P	NF-Tr/Vid, 150V, 0,05A, 0,8W, 120MHz	7c(9mm)	Tos	2SA1019, 2SA1124, 2SA1285A, 2SA1482, ++
2SA95	Ge-P	HF, 20V, 10mA, 50MHz	1g	Fui	AF124..127, AF200, 2SA218..227
2SA950	Si-P	Uni, 35V, 0,8A, 0,6W, 120MHz	7c	Tos,Mic	BC327..328, BC636, BC638, 2SB647, ++
2SA951	Si-P	NF/S-L, 140V, 0,5A, 45MHz	13j	Son	2SA913(A), 2SA1111..1112, 2SA1195, ++
2SA952	Si-P	Uni, 30V, 0,7A, 0,6W, 160MHz	7c	Nec	BC327..328, BC638, 2SB909..910, ++
2SA953	Si-P	Uni, 60V, 0,3A, 0,6W, 100MHz	7c	Nec	BC327A, BC639, 2SA1683, 2SB647, ++
2SA954	Si-P	=2SA953: 60V	7c	Nec	BC640, BCX39, 2N5400..01, 2SB647, ++
2SA955				Nec	—
2SA956	Si-P	SMD, Uni, 60V, 0,1A, 260MHz	35a	Nec	BC856, BCW89, 2SA1311..12
2SA957	Si-P	NF/S-L, 150V, 2A, 30W, 20MHz	17j	Sak	2SA1079, 2SA1133, 2SB628, 2SB861, ++
2SA956	Si-P	=2SA957: 200V	17j	Sak	2SA1133, 2SB861
2SA959	Si-P	S-L, 100V, 10A, 100W	23a	Nec	BUW96, MJ15018, 2SA1118..17, 2SA1147, +
2SA96	Ge-P	HF, 20V, 10mA, 45MHz	1g	Fui	AF124..127, AF200, 2SA218..227
2SA960				Nec	—
2SA961				Nec	—
2SA962	Si-P	Uni-L, 60V, 1,5A, 100MHz	13m	Tos	BD518, BD520, BD526, BD528, BD530
2SA962A	Si-P	=2SA962	13m		(BD816, BD818, BD642, BD644, 2SA887)
2SA963	Si-P	NF/S-L, 50V, 1,5A, 10W, 150MHz	14h	Mat	BD138, BD229, BD378, 2SB674..875, ++
2SA964	Si-P	Vid-L, 200V, 0,2A, 10W, 100MHz	13m	Nec	BF463..465, MPS-U60
2SA964A	Si-P	=2SA964: 250V	13m		BF463..465, MPS-U60
2SA965	Si-P	Uni, 120V, 0,8A, 0,9W, 120MHz	7c(9mm)	Tos	2SA1013, 2SA1275, 2SB647, 2SB1212
2SA966	Si-P	NF-Tr/E, 30V, 1,5A, 0,9W, 120MHz	7c(9mm)	Tos	2SA1392, 2SB978, 2SB892, 2SB1312
2SA967	Si-P	UHF-A, 15V, 0,03A, 4GHz	24b	Tos	BFQ23, BFQ56, BFQ75..76
2SA966	Si-P	NF/S-L, 160/160V, 1,5A, 25W, 100MHz	17j	Tos	2SA1011, 2SA1133, 2SA1112, 2SA1332
2SA968A	Si-P	=2SA968: 180/180V	17j		2SA1011, 2SA1133, 2SA1112, 2SB628A
2SA968B	Si-P	=2SA968: 200/200V	17j		2SA1133, 2SB861
2SA969	Si-P	=2SA968:	22a	Tos	2SA1011, 2SA1133, 2SA1112, 2SA1332
2SA97	Ge-P	HF, 20V, 10mA, 40MHz	1g	Fui	AF124..127, AF200, 2SA218..227
2SA970	Si-P	Uni, ra, 120V, 0,1A, 0,3W, 100MHz	7c	Tos	2SA1038, 2SA1049, 2SA1123, 2SA1139, ++
2SA971	Si-P	NF/S-L, 150V, 15A, 150W, 10MHz	23a	Sak	MJ15016, 2SA908..909, 2SA1116..17, ++
2SA972	Si-P	Uni, 30V, 0,1A, 0,25W, 150MHz	7c	Mat	BC213, BC257, BC308, BC556, ++
2SA973	Si-P	Uni, ra, 80V, 0,05A, 0,25W	7c	Mat	BC214, BC418, BC560, 2SA1138..1137, ++
2SA977	Si-P	NF-L, 180V, 0,05A, 80MHz	14h	Mat	BF470, BF472, 2SA1352..53, 2SA1381, ++
2SA977A	Si-P	=2SA977: 220V	14h		BF470, BF472, 2SA1363, 2SA1361, ++
2SA978	Si-P	Uni, ra, 40V, 0,1A, 0,2W, 125MHz	7b	Mit	BC214, BC416, BC560, 2SA1136..1137, ++
2SA979	Si-P	Dual, ra, 100V, 0,05A, 0,4W, 150MHz	5-SIP	Mit	—
2SA96	Ge-P	HF, 20V, 10mA, 30MHz	1g	Fui	AF124..127, AF200, 2SA218..227
2SA960	Si-P	NF/S-L, 100V, 8A, 60W, 20MHz	23a	Sak	BD246C, BDW52C, 2SB555..556, 2S9681, ++
2SA961	Si-P	=2SA980: 120V	23a	Sak	BD248D, 2N6230..31, 2SB555..56, 2SB681++
2SA982	Si-P	=2SA990: 140V	23a	Sak	BD246D, 2N6231, 2SB555, 2SB681, 2SB697++
2SA963	Si-P	UHF, re, 30V, 20mA, 1GHz	25p	Nec	BF479..480, BF679..680, BF967..970, ++
2SA964	Si-P	Uni, 60V, 0,5A, 0,6W, 120MHz	7c	Say	BC638, 2N5400..01, 2SB647, 2SB1118, ++
2SA964K	Si-P	=2SA984: 100V	7c		BC640, 2N5400..01, 2SA840, 2SB647, ++
2SA965	Si-P	NF/HF-L, 120V, 1,5A, 25W, 180MHz	17j	Nec	2SA968, 2SA1078..1079, 2SB628(A), ++
2SA985A	Si-P	=2SA985: 150V	17j		2SA968, 2SA1079, 2SA1133, 2SB628(A), ++
2SA996	Si-P	NF/S-L, 130V, 7A, 80W, 80MHz	19j	Nec	2SB618, 2SB758A
2SA987	Si-P	Uni, 40V, 0,1A, 0,5W, 90MHz	7c	Nec	BC213, BC257, BC307, BC557, ++
2SA988	Si-P	Uni, 120V, 0,05A, 0,5W, 100MHz	7c	Nec	BF423, 2SA893A, 2SA970, 2SB717(A), ++
2SA989	Si-P	Uni, 80V, 0,1A, 0,25W, 180MHz	7c	Nec	BC212, BC256, BC266, BC556, ++
2SA99	Ge-P	HF, 20V, 10mA, 20MHz	1g	Fui	AF124..127, AF200, 2SA218..227

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2SA990	Si-P	Uni, ra, 60V, 0,1A, 0,25W, 160MHz	7c	Nec	BC214, BC416, BC560, 2SA1136..1137, ++
2SA991	Si-P	Uni, ra, 60V, 0,1A, 0,5W, 90MHz	7c	Nec	BC214, BC416, BC560, 2SA1136..1137, ++
2SA992	Si-P	Uni, ra, 120V, 0,05A, 0,5W, 100MHz	7c	Nec	2SA872A, 2SA941, 2SA970, 2SA1136, ++
2SA993	Si-P	Uni, 50V, 0,5A, 0,625W, 120MHz	7e	Hit	BC327, BC636, 2SA1683, 2SB1116, ++
2SA994	Si-P	Uni, 40V, 0,3A, 0,5W, 120MHz	7b	Mit	BC327, BC638, 2SA1683, 2SB1116, ++
2SA995	Si-P	Dual, 100V, 0,05A, 0,4W, 100MHz	5-SIP	Mit	—
2SA997	Si-P	Uni, 20V, 1A, 0,5W, 150MHz	7c	Fui	BC636, BC638, 2SB647, 2SB909..910, ++
2SA998	Si-P	=2SA997: 50V	7c	Fui	BC636, BC638, 2SB647, 2SB910, ++
2SA999	Si-P	Uni, 50V, 0,2A, 0,3W, 200MHz	7c	Mit	BC212, BC257, BC307, BC557, ++
2SA999L	Si-P	=2SA999: ra	7c		BC416, BC560, 2SA970, 2SA1136..1137, ++
2SB		**2SB**			
2SB100	Ge-P	NF, ra, 30V, 0,05A, 0,1W	2a(B=case)	Nec	AC125..126, AC151r, ACY32, 2SB173
2SB1000	Si-P	SMD, Uni, 25V, 1A, 200MHz	39b	Hit	BC689, BCX51..53, BCX69, 2SA1364, ++
2SB1000A	Si-P	=2SB1000: 30V	39b		BCX51..53, 2SA1213, 2SA1364, 2SB766A, ++
2SB1001	Si-P	SMD, Uni, 20V, 2A, 150MHz	39b	Hit	2SA1314, 2SA1363, 2SB1121, 2SB1313, ++
2SB1002	Si-P	SMD, Uni, 70V, 1A, 150MHz	39b	Hit	BCX53, 2SB803..804, 2SB1025..26, ++
2SB1003	Si-P-Darl+Di	NF/S-L, 60V, 3A, 25W, B=5000	15j	Tos	BD716, BDW24A, BDW54A, 2SB751, ++
2SB1004	Si-P-Darl+Di	NF/S-L, 100V, 4A, 30W, B=4000	15j	Tos	BDW24C, BDW54C, BDW64C, 2SB751B, ++
2SB1005	Si-P-Darl+Di	NF/S-L, 50V, 4A, 30W, B=3000	17j	Sak	BD716, BDW24A, BDW54A, 2SB751, ++
2SB1007	Si-P	NF-L, 60V, 0,7A, 10W, 100MHz	14h	Rhm	BD140, BD231, 2SA1184, 2SA1220, ++
2SB1008	Si-P-Darl+Di	NF/S-L, 40V, 2A, 10W, 150MHz, B>1000	14h	Rhm	BD776, BD778, BD780, 2SB794..795, ++
2SB1009	Si-P	NF/S-L, 40V, 2A, 10W, 100MHz	14h	Rhm	BD376, 2SB1009, 2SA1217, 2SB1217, ++
2SB101	Ge-P	NF, 30V, 0,05A, 0,125W	2a(B=case)	Nec	AC125..126, AC151, 2SB54, 2SB56
2SB1010	Si-P	=2SB1009: 0,75W	7c(9mm)		2SA1315, 2SA1362, 2SB692, 2SB1312, ++
2SB1011	Si-P	S-L, 400/400V, 0,1A, 70MHz	14h	Mat	2SA1156, 2SA1354
2SB1012	Si-P-Darl+Di	NF/S-L 120V, 1,5A, 20W, B>2000	14h	Hit	BD684
2SB1013	Si-P	NF-Tr/E, 20V, 2A, 0,7W	7c	Say	MPS750..751, 2SB733, 2SB736..739, 2SB911
2SB1014	Si-P	NF-Tr/E, 60V, 1A, 0,7W	7c	Say	BC636, BC840, 2SB647, 2SB910, 2SB1041+
2SB1015	Si-P	NF/S-L, 60V, 3A, 25W, 9MHz	17c	Tos	2SA1440, 2SB1015, 2SB1094, 2SB1274, ++
2SB1016	Si-P	NF/S-L, 100V, 5A, 30W, 5MHz	17c	Tos	2SA1441, 2SB1016, 2SB1294
2SB1017	Si-P	NF/S-L, 60V, 4A, 25W, 9MHz	17c	Tos	2SA1441, 2SA1635, 2SB1017, 2SB1335, ++
2SB1018	Si-P	NF/S-L, Io-sat, 100V, 7A, 30W, 10MHz	17c	Tos	BDX78F, 2SA1442
2SB1019	Si-P	NF/S-L, Io-sat, 70V, 7A, 30W, 10MHz	17c	Tos	BDX78F, 2SA1470, 2SB1097, 2SB1290, ++
2SB102	Ge-P	NF-Tr/E, 30V, 0,05A, 0,18W	2a*	Nec	AC128K, AC153K, AC188K, 2N1191..94
2SB1020	Si-P-Darl+Di	NF/S-L, 100V, 7A, 30W, B=2k..15k	17c(B)	Tos	2SB1099, 2SB1228, 2SB1283
2SB1021	Si-P-Darl+Di	=2SB1020: 60V	17c(B)	Tos	2SB1099, 2SB1228, 2SB1283
2SB1022	Si-P-Darl+Di	=2SB1020: 60V	17c(B)	Tos	2SB1099, 2SB1224, 2SB1228, 2SB1283, ++
2SB1023	Si-P-Darl+Di		17c(B)	Tos	2SB1223, 2SB1226, 2SB1257, 2SB1342, ++
2SB1024	Si-P-Darl+Di	NF/S-L, 100V, 4A, 30W, B=4000	15c(B)	Tos	2SB1098, 2SB1227, 2SB1282
2SB1025	Si-P	SMD, Uni, 120/80V, 1A, 140MHz	39b	Hit	2SB1027..1028
2SB1026	Si-P	=2SB1025: 120/100V	39b	Hit	2SB1027..1028
2SB1027	Si-P	SMD, Uni, 180/120V, 1,5A	39b	Hit	—
2SB1028	Si-P	=2SB1027: 180/160V	39b	Hit	—
2SB1029	Si-P	SMD, Uni, 100V, 2A	39b	Hit	2SA1417, 2SB1027..1028
2SB103	Ge-P	NF-Tr/E, 30V, 0,1A, 0,125W	2a	Nec	AC128, AC153, AC168, 2N1191..94
2SB1030	Si-P	=2SB643: 0,3W	40c	Mat	→2SB643
2SB1030A	Si-P	=2SB644: 0,3W	40c		→2SB643
2SB1031	Si-P-Darl+Di	NF/S-L, 100V, 15A, 100W, B>1000	16c(B)	Hit	BDV66A, BDW84C, 2SB969
2SB1032(K)	Si-P-Darl+Di	NF/S-L, 120V, 15A, 80W, B>1000	16c(B)	Hit	BDV84C, BDV68B, BDW84D
2SB1033	Si-P	NF/S-L, 60V, 3A, 40W	17j	Rhm	BD242B, BD538, BD952, 2SA1262, ++
2SB1034	Si-P-Darl+Di	NF/S-L, 60V, 2A, 15W, 50MHz, B=5000	14h	Tos	BD680, BD760, 2N6036, 2SB795
2SB1035	Si-P	Uni, 30V, 1A, 0,9W, 100MHz	7c(9mm)	Mit	2SA968, 2SB764, 2SB978, 2SB1041, ++
2SB1036	Si-P	=2SB788: 0,3W, 200MHz	40c	Mat	→2SB768
2SB1037	Si-P	NF-L, CTV-VA, 150V, 1,5A, 30W, 15MHz	17j	Say	BD240D, 2SB861, 2SA940, 2SB628(A), ++
2SB1038	Si-P	NF/S-L, 60V, 3A, 30W, 20MHz	15j	Nec	BD242A, BD536, BD936, 2SA1268, ++
2SB1039	Si-P	NF/S-L, 100V, 4A, 40W, 20MHz	15j	Nec	BD244C, BD540C, BD954, 2SB862, ++
2SB104	Ge-P	NF-Tr/E, 30V, 0,1A, 0,18W	2a*	Nec	AC128K, AC153K, AC188K, 2N1191..94
2SB1040	Si-P	NF/S-L, 20V, 2A	30j	Nec	2SA1241, 2SA1243, 2SB962, 2SB1182, ++
2SB1041	Si-P	NF/S-L, 80V, 1A, 0,9W	7c(9mm)	Rhm	2SA1013, 2SA1275, 2SB647, 2SB1041
2SB1042(M)	Si-P	=2SB1041: 1W	9c	Rhm	2SA1013, 2SA1275, 2SB647, 2SB1041
2SB1043	Si-P	=2SB1041: 50V	7c(9mm)	Rhm	2SB647, 2SB764, 2SB892, 2SB1041, ++
2SB1044(M)	Si-P	=2SB1041: 50V, 1W	9c	Rhm	2SB647, 2SB784, 2SB692, 2SB1041, ++
2SB1045	Si-P	SMD, Uni, 120V, 0,05A, 140MHz	39b	Hit	2SA1173, 2SA1200, 2SB1046..1047
2SB1046	Si-P	SMD, Uni, 160V, 0,05A, 140MHz	39b	Hit	2SB1047
2SB1047	Si-P	SMD, Uni, 180V, 0,05A, 140MHz	39b	Hit	2SB1046

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2SB1048	Si-P-Darl	SMD, Uni, 60V, 1A, B>2000	39b(D)	Hit	BST60..82, 2SB1126
2SB1049	Si-P	Uni, 30V, 0,1A, 0,4W	9c	Mat	BC213, BC258, BC308, BC558, ++
2SB105	Ge-P	NF-E, 30V, 0,5A, 0,5W	≈2b	Nec	2SB493, (AD162)
2SB1050	Si-P	=2SB873:	9c	Mat	→2SD873
2SB1051	Si-P	SMD, Uni, 40V, 0,3A	≈35d	Rhm	BC607R, BCX17R, BCW67R..68R
2SB1051K	Si-P	=2SB1051: 1A	35a	Rhm	—
2SB1052	Si-P	NF/S-L, 60V, 2A, 25W, 25MHz	17c	Mat	BD936F, 2SB1187, 2SB1314, 2SB1375, ++
2SB1053	Si-P	SMD, Uni, 40V, 0,1A	35a	Mat	BC858..857, BCW69..70, BCW89, ++
2SB1054	Si-P	NF/S-L, 100V, 5A, 60W, 20MHz	16c	Mat	2SB1371..72, (BD246C, BDV96, 2SB668++)
2SB1055	Si-P	=2SB1054: 120V, 6A, 70W	16c	Mat	2SB1361, 2SB1372, (BD246C, 2SA1141++)
2SB1058	Si-P	=2SB1054: 140V, 7A, 60W	16c	Mat	2SB1361, 2SB1372, (BD246D, 2SA1168++)
2SB1057	Si-P	=2SB1054: 150V, 9A, 100W	16c	Mat	2SB1860, (BD246D, 2SA1227A, 2SA1386++)
2SB1058	Si-P	Uni, 20V, 2A, 0,75W, 60MHz	7c	Hit	MPS750, 2SB733, 2SB736..739, 2SB892, ++
2SB1059	Si-P	Uni, 70V, 1A, 0,75W, 65MHz	7c	Hit	BC640, 2SB647, 2SB910, 2SB984, 2SB1041+
2SB106	Ge-P	=2SB106: 3W	≈2b*	Nec	2SB493, (AD162)
2SB1060	Si-P	Uni, 70V, 1A, 1W	9c	Hit	BC640, 2SB647, 2SB910, 2SB984, 2SB1041+
2SB1061	Si-P-Darl	S-L, 300V, 0,3A, 15W, 15MHz, B=5000	17j	Hit, Nec	(2SB1401, 2SB1465)
2SB1062	Si-P	Uni, 15V, 0,5A, 0,6W, 130MHz	9c	Mat	BC327..328, BC636, 2SA1515, 2SB909, ++
2SB1063	Si-P	=2SB1054:	17c	Mat	BD954AF, BDT42AF, 2SB1016, 2SB1294, ++
2SB1064	Si-P	NF/S-L, 60V, 3A, 30W, 70MHz	17j	Rhm	BD242A, BD536, BD936, 2SA1268, ++
2SB1065	Si-P	=2SB1064: 10W	14h	Rhm	BD178, BD190, BD768, 2SB744(A), ++
2SB1066(M)	Si-P	=2SB1064: 1W	9c	Rhm	2SA1707, 2SA1761, 2SB985, 2SB1066
2SB1067	Si-P-Darl+Di	NF/S-L, 60V, 2A, 10W, B=5000	14b(B)	Tos	(BD660, BD760, 2N6036, 2SB795, ++)
2SB1068	Si-P	Uni, 20V, 2A, 0,75W, 180MHz	7c	Nec	MPS750, 2SB733, 2SB738..739, 2SB892, ++
2SB1069	Si-P	NF/S-L, 40V, 4A, 25W, 150MHz	17j	Mat	2SA1012, 2SA1289, 2SB919
2SB1069A	Si-P	=2SB1069: 50V	17j		2SA1012, 2SA1289, 2SB919
2SB107	Ge-P	NF/S-L, 30V, 2A, 10W	23a	Nec	AD149, 2N2137, 2N2142, 2SB449
2SB1070(A)	Si-P	=2SB1069(A):	30j	Mat	2SB1267, (2SA1012, 2SA1289, 2SB919)
2SB1071(A)	Si-P	=2SB1069(A): Iso	17c	Mat	2SA1307, 2SA1469, 2SB953(A)
2SB1072L,S	Si-P-Darl+Di	NF/S-L, 100V, 4A, 20W, B>1000	30j	Hit	2SB908, (BDW24C, BDW54C, 2SB751B, ++)
2SB1073	Si-P	SMD, NF/S, 30V, 4A, 120MHz	39b	Mat	2SB1308, 2SB1386
2SB1074	Si-P	S, 400/400V, 0,5A, 1W	9b	Mat	2SA1625, 2SB1468
2SB1075	Si-P	NF/S-L, 50V, 2A, 150MHz	14h	Mat	BD376, 2SB1065, 2SB1217
2SB1076(M)	Si-P-Darl	Uni, 40V, 2A, 1W, 150MHz, B=20000	9b	Rhm	2SB1129, 2SB865
2SB1077	Si-P-Darl	NF/S-L, 120V, 4A, 40W, B>1000	17c(B)	Hit	BD716, BDW24A, BDW54A, 2SB751, ++
2SB1078	Si-P-Darl	NF/S-L, 120V, 6A, 40W, B>1000	17c(B)	Hit	BD652, BDT20, BDW74D, BDX54D, ++
2SB1079	Si-P-Darl+Di	NF/S-L, 100V, 20A, 100W, B>1000	16c(B)	Hit	2SB1363
2SB107A	Ge-P	=2SB107: 60V	23a		AD166, 2N2137, 2N2142
2SB106	Ge-P	NF-E, 40V, 0,5A, 0,5W	≈2b	Nec	2SB493, (AD162)
2SB1060	Si-P	NF/S-L, 35V, 2A, 10W	17n	Hit	(BD508, BD516, BD526, BD814, ++)
2SB1085	Si-P	NF-L, 120V, 1,5A, 20W, 50MHz	17j	Rhm	BD940, 2SA985(A), 2SA1078, 2SA1393, ++
2SB1065A	Si-P	=2SB1085: 160V	17j		2SA968(A,B), 2SB628(A), 2SA1011, 2SA1332
2SB1066	Si-P	=2SB1085: 10W	14h	Rhm	2SA1021, 2SA1249, 2SB649
2SB1066A	Si-P	=2SB1066: 160V	14h		2SA1249, 2SB649
2SB1087	Si-P-Darl+Di	NF/S-L, 100V, 5A, 30W, B=8000	17j	Nec	BD650, BD902, BDW24C, BDW64C, ++
2SB1068	Si-P-Darl+Di	NF/S-L, 100V, 10A, 60W, B=6000	15j	Nec	BDT62B
2SB1069	Si-P	NF/S-L, 60V, 3A, 30W, 20MHz	17j	Nec	BD242A, BD536, BD936, 2SA1268, ++
2SB106A	Ge-P	=2SB106: 60V	≈2b		—
2SB106B	Ge-P	=2SB106: 60V	≈2b		—
2SB109	Ge-P	=2SB106: 3W	≈2b*	Nec	2SB493, (AD162)
2SB1090	Si-P	NF/S-L, 100V, 4A, 40W, 20MHz	17j	Nec	BD244A, BD536, BD950, 2SA1293, ++
2SB1091	Si-P-Darl	NF/S-L, 100V, 6A, 40W, B>1000	17c(B)	Hit	BD646, BD896, BDW74A, BDX54A, ++
2SB1092	Si-P-Darl	NF/S-L, 60V, 1,5A, 8W, B=10000	14h	Hit	BD680, BD760, 2N6036, 2SB795, 2SB1012
2SB1093	Si-P-Darl+Di	NF/S-L, 60V, 1,5A, 1W, B>2000	9b	Nec	2SB678, 2SB965, 2SB1129, 2SB1406, ++
2SB1094	Si-P	=2SB1089: Iso, 15W	17c	Nec	2SA1394, 2SA1468, 2SB1015, 2SB1274, ++
2SB1095	Si-P	=2SB1090: Iso, 20W	17c	Nec	2SA1441, 2SB1016, 2SB1294, (BD240C, ++)
2SB1096	Si-P	TV, NF-L, 200V, 2A, 25W, 5MHz	17c	Nec	(BD240F, 2SA1133, 2SB630, 2SB720, 2SB661)
2SB1097	Si-P	NF/S-L, 60V, 7A, 30W	17c	Nec	2SA1396, 2SA1442, 2SA1470, 2SB1290
2SB1096	Si-P-Darl+Di	NF/S-L, 100V, 5A, 20W, 80MHz, B=8000	17c(B)	Nec	2SB1258, 2SB1340
2SB1099	Si-P-Darl+Di	NF/S-L, 100V, 6A, 25W, 80MHz, B=6000	17c(B)	Nec	2SB1100, 2SB1284
2SB109A	Ge-P	=2SB106: 60V, 3W	≈2b*		—
2SB109B	Ge-P	=2SB106: 60V, 3W	≈2b*		—
2SB110	Ge-P	NF, 25V, 0,05A, 0,1W, β>18	2a	Nec	AC125..126, AC151, 2SB54, 2SB56
2SB1100	Si-P-Darl+Di	NF/S-L, 100V, 10A, 30W, 60MHz, B=6000	17c(B)	Nec	2SB1264
2SB1101	Si-P-Darl+Di	NF/S-L, 60V, 4A, 40W, B>1000	17c(B)	Hit	BD716, BD718, BDW54A..D, BDW64B..D++
2SB1102	Si-P-Darl+Di	=2SB1101: 60V	17c(B)	Hit	BD718, BDW54B, BDW64B, 2SB885, ++

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2SB1103	Si-P-Darl+Di	NF/S-L, 60V, 8A, 40W, B>1000	17c(B)	Hit	BD646, BD898, BDW74A, BDX54A, ++
2SB1104	Si-P-Darl+Di	=2SB1103: 60V	17c(B)	Hit	BD648, BD900, BDW74B, BDX54B, ++
2SB1105	Si-P-Darl+Di	NF/S-L, 120V, 3A, 30W, B>1000	17c(B)	Hit	BDT60C, BDW54D, 2SB1339
2SB1106	Si-P-Darl+Di	NF/S-L, 120V, 6A, 40W, B>1000	17c(B)	Hit	BD652, BDT20, BDW64D, 2SB1339, ++
2SB1107	Si-P-Darl+Di	NF/S-L, 120V, 10A, 40W, B=5000	17c(B)	Hit	BDT62C, BDX34D
2SB1106	Si-P-Darl	NF/S-L, 120V, 6A, 50W, 30MHz, B>1000	17b	Mat	BD652F, BDT62CF, 2SB1259, 2SB1107
2SB1109	Si-P	NF/Vid-L, 160V, 0,1A, 140MHz	14h	Hit	BF418, BF418, 2SA1352..1353, 2SA1380
2SB111	Ge-P	=2SB110: β>30	2a	Nec	AC125..128, AC151, 2SB54, 2SB56
2SB1110	Si-P	=2SB1109: 200/200V	14h	Hit	BF416, BF418, 2SA1352..1353, 2SA1380
2SB1111	Si-P-Darl+Di	int Z-Di, 60V, 2A, 10W, B>2000	14b	Nec	2SB794..795, 2SB1012
2SB1112	Si-P-Darl+Di	120V, 6A, 40W, B=5000	15c	Hit	BDT20, BD652, BDW64D, 2SB1339, ++
2SB1113	Si-P-Darl+Di	120V, 6A, 40W, B=5000	15c	Hit	BDT20, BD652, BDW74D, 2SB1107, ++
2SB1114	Si-P	SMD, Uni, 20V, 2A, 180MHz	39b	Nec	2SA1203, 2SA1213, 2SA1314, 2SA1369
2SB1115	Si-P	SMD, Uni, Io-sat, 60V, 1A, >80MHz	39b	Nec	2SA1364, 2SB1122..23, 2SB1520
2SB1115A	Si-P	=2SB1115: 80V	39b	Nec	2SB1520
2SB1116	Si-P	Uni, Io-sat, 60V, 1A, 0,75W, 120MHz	7c	Nec	2SA1315, 2SA1706, 2SB892, 2SB1229, ++
2SB1116A	Si-P	=2SB1116: 80V	7c		2SA1315, 2SA1706..09, 2SB1459
2SB1117	Si-P	NF-E, Io-sat, 30V, 3A, 1W, 280MHz	9b	Nip	2SB985, 2SB1505
2SB1118	Si-P	SMD, Io-sat, 20V, 0,7A, 250MHz	39b	Say	2SA1734, (BC869, BCX51..53, BCX69++)
2SB1119	Si-P	SMD, NF, 25V, 1A, 180MHz	39b	Say	BC869, BCX51..53, BCX69, 2SA1314, ++
2SB112	Ge-P	=2SB110: β>43	2a	Nec	AC125..126, AC151, 2SB54, 2SB56
2SB1120	Si-P	SMD, Io-sat, 20V, 2,5A, 250MHz	39b	Say	2SB1301, 2SB1518
2SB1121	Si-P	SMD, Io-sat, 30V, 2A, 150MHz	39b	Say	2SA1681, 2SB1313..14, 2SB1518
2SB1122	Si-P	SMD, NF, Io-sat, 60V, 1A, 150MHz	39b	Say	2SA1384, 2SB1115(A), (BCX52..53, ++)
2SB1123	Si-P	SMD, S, Io-sat, 60V, 2A, 150MHz	39b	Say	2SA1681, 2SB1520, (2SA1417, 2SB1029)
2SB1124	Si-P	SMD, S, Io-sat, 60V, 3A, 150MHz	39b	Say	2SA1738, 2SB1572
2SB1125	Si-P-Darl	SMD, 50V, 0,7A, 170MHz, B>5000	39d	Say	BST61..62
2SB1126	Si-P-Darl	SMD, 50V, 1,5A, 120MHz, B>4000	39c(D)	Say	—
2SB1127	Si-P	Strobo, Io-sat, 25V, 5A, 10W, 320MHz	14h	Say	2SA1120, 2SA1357
2SB1126	Si-P-Darl+Di	NF/S-L, 50V, 2A, 10W, B=5000	14b	Tos	—
2SB1129	Si-P-Darl	NF/S, 50V, 1,5A, 1W, B=10000	39c	Nec	2SB865
2SB113	Ge-P	=2SB110: β>61	2a	Nec	AC125..126, AC151, 2SB54, 2SB56
2SB1130(M)	Si-P	NF-E, 120V, 1,5A, 1W, 50MHz	9c	Rhm	2SB1212, 2SB1236
2SB1130A(M)	Si-P	=2SB1130: 160V	9c		2SA1770, 2SB1212, 2SB1238A
2SB1131	Si-P	=2SB1127: 1W	7c(9mm)	Say, Rhm	2SB1288, 2SB1306
2SB1132	Si-P	SMD, NF-E, 40V, 1A, 150MHz	39b	Rhm	BCX51..53, 2SA1384, 2SB766A, 2SB1123, ++
2SB1133	Si-P	NF-L, 60V, 3A, 25W, 40MHz	17c	Say	2SA1635, 2SA1488, 2SB1094, 2SB1274, ++
2SB1134	Si-P	S-L, Io-sat, 60V, 5A, 25W, 30MHz	17c	Say	2SA1307, 2SA1441, 2SA1469, 2SB1019, ++
2SB1135	Si-P	S-L, Io-sat, 60V, 7A, 30W, 10MHz	17c	Say	2SA1442, 2SA1470, 2SB1018..19
2SB1138	Si-P	S-L, Io-sat, 60V, 12A, 30W, 10MHz	17c	Say	2SA1451..52, 2SA1568, 2SB1468
2SB1137	Si-P-Darl+Di	S-L, 100V, 10A, 65W, B=6000	19c	Nec	2SB1388
2SB114	Ge-P	NF, 25V, 0,05A, 0,1W, B>45	2a	Nec	AC125..126, AC151, 2SB54, 2SB56
2SB1140	Si-P	=2SB1127: Iso	14b	Say	2SA1357
2SB1141	Si-P	NF/S-L, Io-sat, 20V, 1,2A, 10W, 150MHz	14b	Say	2SA1359, 2SB891, (BD138, BD166, BD227)
2SB1142	Si-P	S-L, Io-sat, 60V, 2,5A, 10W, 140MHz	14b	Say	(BD178, BD188, BD440, 2N5194, ++)
2SB1143	Si-P	NF/S-L, Io-sat, 60V, 4A, 10W, 150MHz	14h	Say	(BD188, BD440, BD786, 2SB986, ++)
2SB1144	Si-P	NF/S-L, Io-sat, 120V, 1,5A, 40W, 100MHz	14b	Say	2SA1408, 2SA1507, (2SA1021, 2SA1249)
2SB1145	Si-P-Darl+Di	NF/S-L, 120V, 6A, 20W, B=5000	17c(B)	Hit	BDT60CF, 2SB1340
2SB1146	Si-P-Darl+Di	NF/S-L, 120V, 6A, 25W, B=5000	17c(B)	Hit	BD652F, 2SB1340, 2SB1259
2SB1147	Si-P-Darl+Di	NF/S-L, 120V, 6A, 25W, B=5000	17c(B)	Hit	BD652F, 2SB1259
2SB1148(A)	Si-P	=2SB938(A): 15W	≈30j	Mat	—
2SB1149	Si-P-Darl	NF/S-L, 100V, ±3A, 15W, B=10000	14b	Nec	—
2SB115	Ge-P	=2SB114: B>80	2a	Nec	AC125..126, AC151, 2SB54, 2SB56
2SB1150	Si-P-Darl	NF/S-L, int Z-Di, 80V, 3A, 15W, B=10000	14b	Nec	—
2SB1151	Si-P	Io-sat, 60V, 5A, 20W, <1/3,5µs	14h	Nec	—
2SB1152	Si-P	NF/S-L, 180V, 12A, 120W	18j	Mat	BD746F, 2SA1386(A), 2SA1516, 2SB817, ++
2SB1153	Si-P	NF/S-L, 170V, 15A, 150W	77j	Mat	2SA1302, 2SA1553, 2SB1163
2SB1154	Si-P	NF/S-L, 130V, 10A, 70W, 30MHz	16c	Mat	2SA1672, 2SA1805, (BD246D, 2SA1146, ++)
2SB1155	Si-P	NF/S-L, 130V, 15A, 80W, 25MHz	16c	Mat	2SB1860, (BD746D, 2SA1227, 2SA1386, ++)
2SB1156	Si-P	NF/S-L, 130V, 20A, 100W, 25MHz	16c	Mat	(BD250D, BD746D)
2SB1157	Si-P	NF/S-L, 100V, 5A, 80W, 20MHz	16c	Mat	2SB1371..72, (BD246C, BDV96, 2SA1141, ++)
2SB1156	Si-P	NF/S-L, 120V, 6A, 70W, 20MHz	16c	Mat	2SB1371..72, (BD246D, 2SA1148, 2SA1186)
2SB1159	Si-P	NF/S-L, 140V, 7A, 100W, 20MHz	16c	Mat	2SB1381, (BD246D, 2SA1146, 2SA1188, ++)
2SB116	Ge-P	=2SB114: B>80	2a	Nec	AC125..126, AC151, 2SB54, 2SB56
2SB1160	Si-P	NF/S-L, 150V, 9A, 100W, 20MHz	16c	Mat	(BD246D, 2SA1188, 2SA1227, 2SA1386, ++)
2SB1161	Si-P	NF/S-L, 180V, 12A, 120W, 20MHz	16c	Mat	2SA1673, (BD746F, 2SA1386, 2SB817, ++)

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2SB1162	Si-P	=2SB1161:	77j	Mat	2SA1301..1302, 2SB1153, 2SB1347
2SB1163	Si-P	NF/S-L, 180V, 15A, 150W, 20MHz	77j	Mat	2SA1302, 2SA1553, 2SB1429
2SB1164	Si-P	NF-E, 80V, 2A, 1W	9b	Nec	MPS750..751, 2SA1315, 2SA1429, 2SB892
2SB1165	Si-P	S-L, Io-sat, 80V, 5A, 20W, 130MHz	≈14h	Say	—
2SB1166	Si-P	S-L, Io-sat, 80V, 8A, 20W, 130MHz	≈14h	Say	—
2SB1167	Si-P	S-L, Io-sat, 120V, 3A, 20W, 130MHz	≈14h	Say	—
2SB1166	Si-P	S-L, Io-sat, 120V, 4A, 20W, 130MHz	≈14h	Say	—
2SB1169(A)	Si-P	=2SB954(A): 15W	≈30c	Mat	2SB839, 2SB957..958, 2SB1201
2SB117	Ge-P	=2SB114: B>105	2a	Nec	AC125..126, AC151, 2SB54, 2SB56
2SB1170	Si-P	=2SB1052: 15W	≈30c	Mat	2SB839, 2SB957..958, 2SB1201
2SB1171(A)	Si-P	=2SB928(A): 15W	≈30c	Mat	2SB766, (2SB928(A))
2SB1172(A)	Si-P	=2SB929(A): 15W	≈30c	Mat	2SB906, 2SB1184, 2SB1202
2SB1173(A)	Si-P	=2SB930(A): 15W	≈30c	Mat	2SA1395, 2SA1401, 2SB1203, 2SB1244
2SB1174	Si-P	=2SB931: 15W	≈30c	Mat	—
2SB1175	Si-P	=2SB932: 15W	≈30c	Mat	—
2SB1176	Si-P	=2SB933: 15W	≈30c	Mat	—
2SB1177	Si-P	=2SB934: 15W	≈30c	Mat	—
2SB1178(A)	Si-P-Darl+Di	=2SB937(A): 15W	30c	Mat	2SB907, 2SB1214
2SB1179(A)	Si-P-Darl+Di	=2SB938(A): 15W	30c	Mat	—
2SB118	Ge-P	NF/S-L, 15V, 1,5A, 50W	23a	Mat	AD149, 2N2137, 2N2142, 2SB449, ++
2SB1180(A)	Si-P-Darl+Di	=2SB939(A): 15W	30c	Mat	—
2SB1181(F5)	Si-P	NF-E-L, 80V, 1A, 10W, 100MHz	30j	Rhm	2SB839, 2SB957..958
2SB1182(F5)	Si-P	NF-E-L, 40V, 2A, 10W, 100MHz	30j	Rhm	2SA1241, 2SB838, 2SB1201
2SB1183(F5)	Si-P-Darl	NF-E-L, 40V, 2A, 10W, B>1000	79c(M)	Rhm	2SB907, 2SB1214
2SB1184(F5)	Si-P	NF-E-L, 80V, 8A, 15W, 70MHz	30j	Rhm	2SA1878, 2SB906, 2SB1202
2SB1185	Si-P	=2SB1184: 25W	17c	Rhm	2SA1307, 2SA1440, 2SA1469, 2SB1274
2SB1188	Si-P	NF-E, 120V, 1,5A, 20W, 50MHz	17c	Rhm	2SA1306, 2SA1332, 2SA1393, 2SA1606, ++
2SB1188A	Si-P	=2SB1188: 180V	17c		2SA1306(A,B), 2SA1332, 2SA1606
2SB1187	Si-P	NF-E-L, 80V, 3A, 30W, 12MHz	17c	Rhm	2SA1440, 2SA1469, 2SB1015, 2SB1094, ++
2SB1166	Si-P	SMD, NF, 40V, 2A, 100MHz	39b	Rhm	2SA1213, 2SB1123
2SB1189	Si-P	SMD, NF, 80V, 0,7A, 100MHz	39b	Rhm	BCX53, 2SB803..805, 2SB1025..1026
2SB119	Ge-P	=2SB118: 32V	23a	Mat	AD149, 2N2137, 2N2142, 2SB449, ++
2SB1190	Si-P	NF-L, 200/150V, 1A, 25W, 20MHz	17j	Mat	BD240F, 2SB830, 2SA968B, 2SB861
2SB1190A	Si-P	=2SB1190: 200/180V	17j		BD240F, 2SB630, 2SA968B, 2SB861
2SB1191(A)	Si-P	=2SB1190(A):	30j	Mat	2SB928, (2SB830, 2SA968B, 2SB861)
2SB1192(A)	Si-P	=2SB1190(A):	17c	Mat	2SA1306B, 2SA1668, 2SB1096, 2SB1530
2SB1193	Si-P-Darl	NF-L, 120V, 8A, 50W, 15MHz, B>1000	17c(B)	Mat	BD852F, BDT62CF, 2SB1259
2SB1194	Si-P-Darl	NF-L, 100V, 5A, 30W, 30MHz, B>1500	17c(B)	Mat	2SB1098, 2SB1227, 2SB1258, 2SB1340
2SB1195	Si-P-Darl	NF-L, 100V, 8A, 50W, B=5000	17c	Mat	2SB1099..1100, 2SB1284
2SB1196	Si-P	NF-L, 70V, 4A, 25W	15c	Hit	2SA1394, 2SA1469, 2SB1019, 2SB1095, ++
2SB1197K	Si-P	SMD, NF, 40V, 0,8A, 200MHz	35a	Rhm	BCW67..66
2SB1198K	Si-P	SMD, NF, 80V, 0,5A, 180MHz	35a	Rhm	BCX42
2SB1199	Si-P	NF, 15V, 1A, 0,3W	9c	Rhm	BC327..328, 2SA1515
2SB119A	Ge-P	=2SB118: 80V	23a		AD188..187, 2N2139, 2N2144, ++
2SB12	Ge-P	NF, 30V, 0,05A, 0,05W	5g	Fui	AC125..126, AC151, 2SB54, 2SB56
2SB120	Ge-P	NF, 32V, 0,02A, 0,15W	2a	Fui	AC125..126, AC151, 2SB54, 2SB56
2SB1201	Si-P	S-L, Io-sat, 80V, 2A, 15W, 150MHz	30j	Say	—
2SB1202	Si-P	S-L, Io-sat, 80V, 3A, 15W, 150MHz	30j	Say	2SA1244
2SB1203	Si-P	S-L, Io-sat, 80V, 5A, 20W, 130MHz	30j	Say	2SA1244
2SB1204	Si-P	S-L, Io-sat, 80V, 8A, 20W, 130MHz	30j	Say	—
2SB1205	Si-P	S-L, Io-sat, 25V, 5A, 10W, 320MHz	30j	Say	—
2SB1206	Si-P	=2SB774: 0,5W	40c	Mat	→2SB774
2SB1207	Si-P	Uni, 15V, 0,5A, 0,3W, 130MHz	40c	Mat	BC327..328, BC636, 2SA1515, 2SB909, ++
2SB1206	Si-P	SMD, Rbe=10kΩ, NF, 20V, 2A, 120MHz	39b	Mat	(2SA1213, 2SA1314, 2SA1363, 2SB1121, ++
2SB1209	Si-P	NF/S, 400/400V, 0,1A, 1W, 70MHz	9c	Mat	2SA1363, 2SA1372, 2SA1584, 2SA1780
2SB121	Ge-P	NF/S, 105V, 0,1A, 0,05W	2a	Fui	ACY39, 2N4042..4043
2SB1210	Si-P	NF, 20V, 2A, 0,5W, 80MHz	7c	Rhm	MPS750, 2SB733, 2SB736..739, 2SB892, ++
2SB1211	Si-P	=2SB1210: SMD	39b	Rhm	2SA1213, 2SA1314, 2SA1363, 2SB1121, ++
2SB1212	Si-P	NF, 180V, 1,5A, 0,9W, 50MHz	7c(9mm)	Rhm	2SA1770, 2SB1130A, 2SB1236A
2SB1213	Si-P-Darl+Di	NF/S-L, 120V, 10A, 30W, B=5000	15c	Hit	BDT82CF, 2SB1259
2SB1214	Si-P-Darl+Di	NF/S-L, 80V, 3A, 15W, B=5000	30c, 79c(B)	Say	2SB906, 2SB1072, 2SB1303
2SB1215	Si-P	S-L, Io-sat, 120V, 3A, 20W, 130MHz	30j	Say	2SA1847
2SB1216	Si-P	S-L, Io-sat, 120V, 4A, 20W, 130MHz	30j	Say	2SA1847
2SB1217	Si-P	NF/S-L, Io-sat, 80V, 3A, 10W, 50MHz	14h	Nec	2SB988
2SB1218	Si-P	=2SB709:	35a(2mm)	Mat	2SA1576, 2SA1586, 2SA1603, 2SA1622
2SB1218A	Si-P	=2SB709A:	35a(2mm)		2SA1576, 2SA1586, 2SA1603, 2SA1622

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2SB1219	Si-P	=2SB710:	35a(2mm)	Mat	2SA1577, 2SA1586
2SB1219A	Si-P	=2SB710A:	35a(2mm)		—
2SB122	Ge-P	NF/S-L, 80V, 1,5A, 20W	23a	Tos	AD 167, 2N2141, 2N2146
2SB1220	Si-P	=2SB792:	35a(2mm)	Mat	2SA1609
2SB1221	Si-P	Vid, 250/200V, 0,07A, 1W, 80MHz	7c(9mm)	Mat	BF 423A, BF 436, BF 492, 2SA1371..72,++
2SB1222	Si-P	SMD, S, 40V, 0,2A, -/<300ns	35a	Mat	BSR 15..16, BSR 16, 2SA1338
2SB1223	Si-P-Darl+Di	NF/S-L, 70V, 4A, 20W, 20MHz, B=5000	15c(B)	Say	2SB1024, 2SB1098, 2SB1282, 2SB1342, ++
2SB1224	Si-P-Darl+Di	NF/S-L, 70V, 7A, 25W, 20MHz, B=5000	15c(B)	Say	2SB1021, 2SB1099, 2SB1226, 2SB1283, ++
2SB1225	Si-P-Darl+Di	NF/S-L, 70V, 10A, 30W, 20MHz, B=5000	15c(B)	Say	2SB1100, 2SB1259, 2SB1284
2SB1226	Si-P-Darl+Di	NF/S-L, 110V, 3A, 20W, 20MHz, B=4000	15c(B)	Say	BDT 60CF, 2SB1340
2SB1227	Si-P-Darl+Di	NF/S-L, 110V, 5A, 25W, 20MHz, B=4000	15c(B)	Say	2SB1340, 2SB1344
2SB1228	Si-P-Darl+Di	NF/S-L, 110V, 8A, 30W, 20MHz, B=4000	15c(B)	Say	2SB1193, 2SB1259, 2SB1344
2SB1229	Si-P	S, Io-sat, 80V, 2A, 0,75W, 150MHz	7c	Say	2SA1706, 2SB892, 2SB1312, 2SB1433, ++
2SB123	Ge-P	NF/S-L, 40V, 5A, 20W	23a	Tos	AD166..167, 2N1529..38, 2N1539..46,++
2SB1230	Si-P	NF/S-L, Io-sat, 110V, 15A, 100W	18j	Say	—
2SB1231	Si-P	NF/S-L, Io-sat, 110V, 25A, 120W	18j	Say	—
2SB1232	Si-P	NF/S-L, Io-sat, 110V, 40A, 150W	18j	Say	—
2SB1233(A)	Si-P	=2SB1192(A): 15W	≈30c	Mat	2SB766, 2SB842, (2SB926(A))
2SB1234	Si-P-Darl	=2SB1235: SMD	35a(D)	Say	BCV 46
2SB1235	Si-P-Darl	NF, 50V, 0,2A, B>5000	40c(D)	Say	—
2SB1236	Si-P	=2SB1130, A(M,AM): Pins=14mm	9c	Rhm	→2SB1130..
2SB1237	Si-P	=2SB909: Pins=14mm	9c	Rhm	→2SB909
2SB1238	Si-P	=2SB910: Pins=14mm	9c	Rhm	→2SB910
2SB1239	Si-P-Darl	=2SB1076(M): Pins=14mm	9b(M)	Rhm	→2SB1076
2SB124	Ge-P	S-L, 60V, 15A, 40W		Tos	(2N1550..52, 2N1554..56, 2N1558..80,++)
2SB1240	Si-P	=2SB911: Pins=14mm	9c	Rhm	→2SB911
2SB1241	Si-P	Uni, 80V, 1A, 1W	9c	Rhm	BC640, BCX23, BCX39, 2SB647, ++
2SB1242	Si-P	Uni, 50V, 1A, 1W	9c	Rhm	BC 327, BC 638, BC 640, 2SB847, ++
2SB1243	Si-P	=2SB1066: Pins=14mm	9c	Rhm	→2SB1066
2SB1244	Si-P	Vid, 160/180V, 0,1A, 0,9W, 140MHz	7c(9mm)	Hit	BF 423A, BF 435, BF 491, 2SA1370..72, ++
2SB1245	Si-P	=2SB1244: 200/200V	7c(9mm)	Hit	BF 423A, BF 436, BF 491, 2SA1370..73, ++
2SB1246	Si-P	NF/S-L, 40V, 2A, 10W	30j	Mit	2SA1241, 2SB836, 2SB1182, 2SB1201, ++
2SB1247	Si-P	NF/S-L, 60V, 1,5A, 10W	30j	Mit	2SB839, 2SB957..960, 2SB1201..02,++
2SB1248	Si-P	NF/S-L, 110V, 0,8A, 10W	30j	Mit	2SA1592, 2SB844..845, 2SB959..980,++
2SB1249	Si-P	NF/S-L, 130V, 0,8A, 10W	30j	Mit	2SA1225, 2SB640..842, 2SB905, 2SB1275,++
2SB125	Ge-P	=2SB124: 36V		Tos	(2N1549..52, 2N1553..56, 2N1557..80,++)
2SB1250	Si-P-Darl	NF/S-L, 100V, 3A, 35W, 20MHz, B>5000	17c	Mat	2SB1098, 2SB1251..52, 2SB1430
2SB1251	Si-P-Darl	NF/S-L, 110V, 4A, 40W, 20MHz, B>5000	17c	Mat	2SB1098, 2SB1252, 2SB1430
2SB1252	Si-P-Darl	NF/S-L, 120V, 5A, 45W, 20MHz, B>5000	17c	Mat	—
2SB1253	Si-P-Darl	NF/S-L, 130V, 6A, 50W, 20MHz, B>5000	16c	Mat	2SB1254..55, 2SB1587..88
2SB1254	Si-P-Darl	NF/S-L, 160V, 7A, 70W, 20MHz, B>5000	16c	Mat	2SB1255, 2SB1567..66
2SB1255	Si-P-Darl	NF/S-L, 160V, 8A, 100W, 20MHz, B>5000	16c	Mat	2SB1566
2SB1256	Si-P-Darl+Di	NF/S, 100V, 2A, 1,2W, B=2000	7c	Rhm	2SB1367, 2SB1316
2SB1257	Si-P-Darl+Di	NF/S-L, 80V, 4A, 25W, 200MHz, B>2000	17c(B)	Sak	2SB1282, (2SB1098, 2SB1223, 2SB1342,++)
2SB1258	Si-P-Darl+Di	NF/S-L, 100V, 8A, 30W, 100MHz, B>1000	17c(B)	Sak	2SB1283, (2SB1099, 2SB1226, 2SB1340,++)
2SB1259	Si-P-Darl+Di	NF/S-L, 120V, 10A, 30W, B>2000	17c(B)	Sak	BDT 62CF, BDT64CF
2SB126	Ge-P	NF/S-L, 32V, 3,5A, 30W	23a	Mat	AD 149, AD 166..167, AL 102..103,++
2SB1260	Si-P	SMD, NF, 80V, 1A, 100MHz	39b	Rhm	BCX53, 2SB803..804, 2SB1025..1026
2SB1261(Z)	Si-P	NF/S-L, 60V, 3A, 10W, 50MHz, <0,5/2,5µs	30j	Nec	2SB906, 2SB1184, 2SB1202
2SB1262	Si-P-Darl+Di	NF/S-L, 80V, 4A, 25W, B=5000	15c	Hit	2SB1257, 2SB1223, 2SB1342
2SB1263	Si-P-Darl+Di	NF/S-L, 80V, 8A, 25W, B=5000	15c	Hit	2SB1020..21, 2SB1099, 2SB1224
2SB1264	Si-P	=2SB1221: 0,6W	9c	Mat	BF 423A, BF 436..437, 2SA1371, ++
2SB1265	Si-P	NF, 400/400V, 0,1A, 1W	9c	Mat	2SA1024, 2SA1372, 2SA1251, 2SB1209, ++
2SB1266	Si-P	NF/S-L, 80V, 3A, 30W, 8MHz	30c	Say	2SB929..930(A), (BD936, BD540A,++)
2SB1267	Si-P	S-L, Io-sat, 80V, 8A, 30W, 120MHz	30c	Say	—
2SB1268	Si-P	S-L, Io-sat, 80V, 5A, 30W, 30MHz	30c	Say	2SB1270, 2SB1449, 2SB1451
2SB1269	Si-P	S-L, Io-sat, 80V, 7A, 40W, 10MHz	30c	Say	2SB1271, 2SB1450, 2SB1452
2SB126A	Ge-P	=2SB126: 80V	23a		AD166..167, AL 102..103, 2SB231,++
2SB127	Ge-P	NF/S-L, 32V, 3,5A, 30W	23a	Mat	AD149, AD 166..167, AL 102..103,++
2SB1270	Si-P	S-L, Io-sat, 90V, 5A, 30W, 20MHz	30c	Say	2SB1451..52
2SB1271	Si-P	S-L, Io-sat, 90V, 7A, 40W, 20MHz	30c	Say	2SB1452
2SB1272	Si-P-Darl+Di	NF/S-L, 100V, 2A, 10W, B>1000	14b	Rhm	BD682, 2SB1012
2SB1273	Si-P	NF-L, 80V, 3A, 30W, 100MHz	17j	Say	2SA1012, 2SA1266, 2SA1293, 2SB1064
2SB1274	Si-P	=2SB1273: Iso, 20W	17c	Say	2SA1307, 2SA1440, 2SA1469, 2SB1185
2SB1275(F5)	Si-P	NF/S-L, 180V, 1,5A, 10W, 50MHz	30j	Rhm	2SA1225, 2SA1552, 2SB840..842,++
2SB1276	Si-P	=2SB737: Pins=14mm	9c	Rhm	→2SB737

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2SB1277	Si-P	=2SB822: Pins=14mm	9c	Rhm	→2SB822
2SB1278	Si-P	=2SB851: Pins=14mm	9c	Rhm	→2SB851
2SB1279	Si-P	NF, 15V, 0,2A, 0,3W	9c	Rhm	BC213, BC258, BC308, BC558, 2SA1515+
2SB127A	Ge-P	=2SB127: 60V	23a		AD166..167, AL102..103, 2SB231, ++
2SB128	Ge-P	NF/S-L, 60V, 6A, 30W	23a	Mat	AL102..103, 2N3615..3618
2SB1280	Si-P-Darl+Di	NF/S-L, 120V, 3A, 25W, B=5000	15c	Hit	2SB1252, 2SB1340
2SB1281	Si-P-Darl+Di	NF/S-L, 120V, 6A, 25W, B=5000	15c	Hit	2SB1193, 2SB1340
2SB1282	Si-P-Darl+Di	NF/S-L, 100V, ±4A, 25W, 50MHz, B>1500	17c(B)	Shi	BDT60BF, 2SB1024, 2SB1194, 2SB1361, ++
2SB1283	Si-P-Darl+Di	NF/S-L, 100V, 7A, 30W, 50MHz, B>1500	17c(B)	Shi	BD650F, 2SB1020, 2SB1099, 2SB1431, ++
2SB1284	Si-P-Darl	NF/S-L, 100V, 10A, 35W, 50MHz, B>1500	17c(B)	Shi	2SB1100, 2SB1259, 2SB1432
2SB1285	Si-P-Darl	NF/S-L, 100V, 15A, 100W, 50MHz, B>1500	17c(B)	Shi	BDV66A..D, BDW84C..D
2SB1286	Si-P-Darl+Di	NF/S-L, 100V, 2A, 25W, B>1000	17c(B)	Rhm	BDW24C, BDW54C, BDW64C, 2SB751B, ++
2SB1287	Si-P-Darl+Di	=2SB1286: Iso, 20W	17c(B)	Rhm	2SB1024, 2SB1098, 2SB1282
2SB1288	Si-P	DC-DC-Converter, 30V, 5A, 1W, 120MHz	7c(9mm)	Mat	2SB1306, 2SB1319, 2SB1398
2SB1289	Si-P	NF/S-L, 80V, 7A, 40W, 12MHz	17j	Rhm	BD544C, BD712, BD602, 2SB870, ++
2SB128A	Ge-P	=2SB128: 120V	23a		AL100, AL102, 2N2290, 2N2293
2SB129	Ge-P	NF/S-L, 80V, 6A, 30W	23a	Mat	AL102..103, 2N3615..3618
2SB1290	Si-P	=2SB1289: Iso, 30W	17c	Rhm	2SA1398, 2SA1442, 2SA1851, 2SB1018
2SB1291	Si-P	NF-L, 60V, 5A, 40W, 12MHz	17j	Rhm	BD244B, BD544B, BD952, 2SA1012, ++
2SB1292	Si-P	=2SB1291: Iso, 30W	17c	Rhm	BD950F, 2SA1394, 2SA1469, 2SB1097, ++
2SB1293	Si-P	=2SB1291: 100V	17j	Rhm	BD244C, BD544C, BD954, 2SB833, ++
2SB1294	Si-P	=2SB1291: Iso, 100V, 30W	17c	Rhm	BD954F, 2SA1388, 2SA1441, 2SB1016, ++
2SB1295	Si-P	=2SB1296: SMD	35a	Say	BCW67..68, 2SA1621, 2SB1197
2SB1296	Si-P	NF, lo-sat, 15V, 0,8A, 0,3W, 300MHz	40c	Say	2SA1705, 2SB1118, (BC327..328, ++)
2SB1297	Si-P	NF, 120V, 0,5A, 1W, 250MHz	7c(9mm)	Mat	2SA840, 2SA965, 2SB847, 2SB987, ++
2SB1298	Si-P	NF, 40V, 2A, 1,2W	7c(9mm)	Rhm	2SA1315, 2SA1382, 2SB892, 2SB1312, ++
2SB1299	Si-P	hi-beta, 80V, 3A, 40W, 30MHz, B>300	17c	Mat	—
2SB129A	Ge-P	=2SB129: 120V	23a		AL100, AL102, 2N2290, 2N2293
2SB13	Ge-P	NF, 30V, 0,05A, 0,05W	5g	Fui	AC125..126, AC151, 2SB54, 2SB56
2SB130	Ge-P	NF/S-L, 32V, 1,5A, 6,5W	22a	Mat	AD162, 2SB474
2SB1300	Si-P	NF/S, lo-sat, 20V, 3A, 0,75W, 140MHz	7c	Nec	2SB893, 2SB985, 2SB1117, 2SB1505, ++
2SB1301	Si-P	=2SB1300: SMD	39b	Nec	2SA1736, 2SB1124, 2SB1518
2SB1302	Si-P	SMD, S, lo-sat, 25V, 5A, 320MHz	39b	Say	(2SB1073)
2SB1303	Si-P-Darl+Di	NF/S-L, 110V, 3A, 10W, 20MHz, B>1500	30c	Say	2SB908, 2SB1072
2SB1304	Si-P	NF/S-L, 100V, 4A, 20W	15c	Hit	2SA1441, 2SB1016, 2SB1095, 2SB1294, ++
2SB1305	Si-P	NF, 30V, 5A, 0,75W, 120MHz	7c	Rhm	2SB1050, 2SB1266, 2SB1326, 2SB1398, ++
2SB1306	Si-P	=2SB1305: 1,2W	7c(9mm)	Rhm	2SB1288, 2SB1448
2SB1307(M)	Si-P	=2SB1305: 0,3W	9c	Rhm	2SB1050, 2SB1266, 2SB1326, 2SB1398, ++
2SB1308	Si-P	=2SB1305: SMD	39b	Rhm	2SB1073
2SB1309	Si-P	NF-L, 60V, 0,7A, 5W, 100MHz	14b	Rhm	2SB869, 2SB1142, (BD140, BD170, BD236)
2SB131	Ge-P	NF/S-L, 40V, 1,5A, 65W	23a	Fui	AD149, 2N2136, 2N2143
2SB1310	Si-P-Darl	NF/S-L, 40V, 2A, 5W, B>1000	14b	Rhm	(BD676, BD776, 2SB794..795, 2SB1008, +)
2SB1311	Si-P	NF/S-L, 40V, 2A, 5W	14b	Rhm	2SA1359, 2SB891, 2SB1142
2SB1312	Si-P	NF, 50V, 2A, 1,2W	7c(9mm)	Rhm	2SA1315, 2SA1382, 2SB892, 2SB1312, ++
2SB1313	Si-P	=2SB1312: SMD	39b	Rhm	2SA1213, 2SB1123..1124
2SB1314	Si-P	lo-sat, hi-beta, 60V, 3A, 15W, 100MHz	17c	Mit	—
2SB1315	Si-P	NF/S-L, 120V, 5A, 65W, 65MHz	18c	Mit	2SA1871..72, 2SA1804..05, 2SA1908..09, ++
2SB1316(F5)	Si-P-Darl+Di	NF/S-L, 100V, 2A, 10W, B=3000	30j	Rhm	2SB908, 2SB1072, 2SB1303
2SB1317	Si-P	NF/S-L, 180V, 15A, 150W, 20MHz	17j	Mat	2SA1302, 2SA1553
2SB1318	Si-P-Darl+Di	Uni, 100V, ±3A, 1W, B>2000	9b	Nec	2SB1484
2SB1319	Si-P	=2SB1288:	9c	Mat	→2SB1266
2SB131A	Ge-P	=2SB131: 6A	23a		AL100..101, 2N2288, 2N2291
2SB132	Ge-P	=2SB131: 60V	23a	Fui	AD166..167, 2N2139, 2N2144
2SB1320	Si-P	=2SB841: Pins=14mm	9c	Mat	→2SB841
2SB1320A	Si-P	=2SB642: Pins=14mm	9c		→2SB642
2SB1321	Si-P	=2SB643: Pins=14mm	9c	Mat	→2SB843
2SB1321A	Si-P	=2SB644: Pins=14mm	9c		→2SB844
2SB1322(A)	Si-P	=2SB793(A): Pins=14mm	9c	Mat	→2SB792(A)
2SB1323	Si-P+Di+R	Motor-Tr, 40V, 3A, Rb=160Ω, Rbe=800Ω	39b	Say	—
2SB1324	Si-P+Di+R	=2SB1323: Rb=0Ω, Rbe=800Ω	39b	Say	—
2SB1325	Si-P+Di+R	=2SB1323: 25V, 5A, Rb=0Ω, Rbe=1,5kΩ	39b	Say	—
2SB1326	Si-P	=2SB1307: Pins=14mm	9c	Rhm	→2SB1307
2SB1327	Si-P	HF-L, 100V, 5A, 58,3W	49d	Mit	—
2SB1328	Si-P	Uni, 160/160V, 1,5A, 1,2W, 50MHz	78b	Rhm	2SA1225, 2SA1552, 2SB1275, 2SB1409
2SB1329	Si-P	lo-sat, 40V, 1A, 1,2W, 150MHz	78b	Rhm	2SA1241, 2SB1201
2SB132A	Ge-P	=2SB131: 60V, 6A	23a		AL100..101, 2N2289, 2N2292

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2SB1330	Si-P	lo-sat, 80V, 0,7A, 1,2W, 100MHz	78b	Rhm	—
2SB1331	Si-P	lo-sat, 40V, 2A, 1,2W, 100MHz	78b	Rhm	2SA1241, 2SB1201
2SB1332	Si-P	lo-sat, 80V, 1A, 1,2W, 100MHz	78b	Rhm	2SA1593
2SB1333	Si-P-Darl+Di	=2SB1256	78b	Rhm	2SB908, 2SB1072, 2SB1303
2SB1334(A)	Si-P	NF-L, 80V, 4A, 40W, 12MHz	17j	Rhm	BD244B, BD538, BD952, 2SB920L, ++
2SB1335(A)	Si-P	=2SB1334: Iso, 30W	17c	Rhm	2SA1394, 2SA1635, 2SB1095, 2SB1292, ++
2SB1337	Si-P	NF/S-L, 150V, 2A, 40W	17j	Rhm	BD242D, 2SA940, 2SB861, 2SB991, ++
2SB1338	Si-P	=2SB1337: Iso, 30W	17c	Rhm	2SA1332. 2SB1096, 2SB1530
2SB1339	Si-P-Darl+Di	NF/S-L, 120V, 6A, 40W, 12MHz. B=10000	17j	Rhm	—
2SB134	Ge-P	NF, ra, 30V, 0.1A, 0,1W	2a	Mit	AC125..126. AC151r. ACY32. 2SB173
2SB1340	Si-P-Darl+Di	=2SB1339: Iso, 30W	17c		—
2SB1341	Si-P-Darl+Di	NF/S-L, 80V, 4A, 40W, 12MHz, B=3000	17c(B)	Rhm	BD718, BDW24B, BDW54B, BDW64B, ++
2SB1342	Si-P-Darl+Di	=2SB1341: Iso, 30W	17c(B)		2SB1024, 2SB1098, 2SB1227, 2SB1282, ++
2SB1343	Si-P-Darl+Di	NF/S-L, 100V, 8A, 40W, 12MHz, B=10000	17c(B)	Rhm	BD652, BD9022, BDW47C, BDX54C, ++
2SB1344	Si-P-Darl+Di	=2SB1343: Iso, 30W	17c(B)	Rhm	BD650F, 2SB1020, 2SB1099, 2SB1263, ++
2SB1345	Si-P	NF/S-L, 100V, 7A, 80W, 12MHz	16c	Rhm	(BD246C, BDV96, 2SA1141, 2SA1186, ++)
2SB1346	Si-P	NF/S-L, 60V, 3A, 30W, 40MHz	17j	Say	BD242A, BD536, BD938, 2SA1262, ++
2SB1347	Si-P	NF/S-L, 180V, 12A, 120W, 15MHz	7j	Say	2SA1301..02, 2SB1153, 2SB1162..63
2SB1348	Si-P	NF, 160/180V, 0,1A, 0,4W, 140MHz	7c	Hit	BF423A, BF435..437, 2SA1281, ++
2SB1349	Si-P	=2SB1348: 200/200V	7c	Hit	BF423A, BF435..437, 2SA1370, ++
2SB135	Ge-P	NF, 30V, 0,1A, 0,1W	2a	Mit	AC125..126, AC151, 2SB54, 2SB56
2SB1351	Si-P-Darl+Di	NF/S-L, 80V, 12A, 30W, B>2000	17c(B)	Sak	BDT64(A..C)F, (BDW45, BDW94A)
2SB1352	Si-P-Darl+Di	=2SB1351: 60W	16c(B)	Sak	BDV64F, BDV86F, (BDW84A)
2SB1353	Si-P	NF/S-L, 120V, 1,5A, 1,8W, 50MHz	76c	Rhm	2SB1086, 2SB1144, 2SB1220(A)
2SB1353A	Si-P	=2SB1353: 180V	76c		2SA1249, 2SB649, 2SB1086A
2SB1354	Si-P	NF/S-L, 60V, 3A, 1,8W	76c	Rhm	BD178, BD440, 2N5194, 2SB1217, ++
2SB1355	Si-P	NF/S-L, 80V, 4A, 1,8W, 12MHz	76c	Rhm	BD788, BD790, MJE250..252, 2N5195
2SB1356	Si-P	NF/S-L, 80V, 7A, 1,8W, 12MHz	76c	Rhm	—
2SB1357	Si-P	NF/S-L, 60V, 3A, 1,8W, 70MHz	76c	Rhm	2SB1085, 2SB1217
2SB1358	Si-P	NF/S-L, 80V, 5A, 1,8W, 12MHz	76c	Rhm	2SB1151
2SB1359	Si-P-Darl+Di	NF/S-L, 100V, 2A, 1,8W, B>1000	17c(B)	Rhm	—
2SB135A	Ge-P	=2SB135: 110V	2a		ACY39, 2N2042..2043
2SB138	Ge-P	NF, 25V, 0,15A, 0,15W	2a	Mit	AC125..126, AC151, 2SB54, 2SB56
2SB1360	Si-P	NF/S-L, 100V, 5A, 1,8W, 12MHz	76c	Rhm	—
2SB1391	Si-P	NF/S-L, 150V, 9A, 100W, 15MHz	16c	Mat	2SA1873, (BD246D, 2SA1186, 2SA1386(A)+)
2SB1362	Si-P	=2SB1361	18j	Mat	BD246D, 2SA1186, 2SA1386(A), 2SB617, ++
2SB1363	Si-P	NF/S, 400/360V, 0,1A, 0,9W	7c(9mm)	Hit	2SA1024, 2SA1372, 2SA1584, 2SA1760, ++
2SB1364	Si-P	SMD, NF, 30V, 1A	39b	Hit	BCX51..53, 2SA1364, 2SB786A, 2SB1260, ++
2SB1365	Si-P	SMD, NF, 20V, 2A	39b	Hit	2SA1383, 2SA1663, 2SB1121, 2SB1301, ++
2SB1386	Si-P	NF/S-L, 80V, 3A, 25W, 9MHz	17c	Kec	2SA1440, 2SA1486, 2SA1635, 2SB1335, ++
2SB1387	Si-P	NF/S-L, 100V, 5A, 30W, 5MHz	17c	Kec	BD954F, 2SA1441, 2SB1016, 2SB1294, ++
2SB1386	Si-P	NF/S-L, 80V, 4A, 25W, 9MHz	17c	Kec	2SA1441, 2SA1635, 2SA1394, 2SB1335, ++
2SB1389	Si-P	NF/S-L, 80V, 3A, 40W, 15MHz	17j	Rhm	BD242, BD536, BD936, 2SA1262, ++
2SB138A	Ge-P	=2SB136: 80V	2a		ACY24, ASY48, ASY77, 2SB55
2SB137	Ge-P	NF/S-L, 30V, 5A, 30W	23a	Mit	AD186..167, AL102..103, 2SB231, ++
2SB1370	Si-P	=2SB1389: Iso, 30W	17c	Rhm	2SA1488, 2SA1635, 2SB1094, 2SB1335, ++
2SB1371	Si-P	NF/S-L, 120V, 6A, 70W, 15MHz	16c	Mat	2SA1671, (BD248D, 2SA1146, 2SA1186, ++)
2SB1372	Si-P	NF/S-L, 140V, 7A, 80W, 15MHz	16c	Mat	2SA1672, (BD248D, 2SA1146, 2SA1186, ++)
2SB1373	Si-P	NF/S-L, 160V, 12A, 120W, 15MHz	18j	Mat	BD746F, 2SA1386(A), 2SA1492, 2SA1516
2SB1374	Si-P	lo-sat, 50V, 2A, 1W, 200MHz	7c(9mm)	Rhm	2SA1315, 2SA1706, 2SB892, 2SB1434
2SB1375	Si-P	NF-L, 80V, 3A, 25W, 9MHz, B=100..320	17c	Tos	BD938F, 2SB1015, 2SB1094, 2SB1274, ++
2SB1376	Si-P	Uni, 50V, 0,1A, 1W, 80MHz	9c	Mat	BC212, BC257, BC307, BC557, ++
2SB1377	Si-P	Uni, 50V, 0,5A, 1W, 200MHz	9c	Mat	BC327, BC638, BC840, 2SA1705, ++
2SB1378	Si-P	Uni, 25V, 0,5A, 0,6W, 150MHz	9c	Mat	BC327..328, BC638, BC638, 2SA1515, ++
2SB138	Ge-P	=2SB137: 80V	23a	Mit	AD186..167, AL102..103, 2SB231, ++
2SB1381	Si-P-Darl+Di	NF/S-L, 100V, 5A, 30W, B=1,5k..15k	17c(B)	Tos	2SB1098, 2SB1227..26, 2SB1258, 2SB1340++
2SB1382	Si-P-Darl+Di	NF/S-L, 120/120V, 16A, 75W, B>2000	16c(B)	Sak	BDV66CF..DF
2SB1363	Si-P-Darl+Di	NF/S-L, 120/120V, 25A, 120W, B>2000	16c(B)	Sak	2SB1494
2SB1386	Si-P	=2SB1305: SMD	39b	Rhm	2SB1308
2SB1387	Si-P-Darl+Di	NF-E, 120V, 1,5A, 1W, 120MHz, B>2000	7c	Hit	2SB1256
2SB1386	Si-P-Darl+Di	110V, 10A, 45W, 20MHz, B=4000	16c	Say	BDV64CF, BDV66BF..DF, (BDW84D)
2SB1389	Si-P-Darl+Di	=2SB1101: Iso, 25W	17c(B)	Hit	BDT80F, 2SB1223, 2SB1257, 2SB1342, ++
2SB138A, B	Ge-P	=2SB137: 80V	23a	Mit	AD167, AL102..103, 2SB231, ++
2SB1390	Si-P-Darl+Di	=2SB1103: Iso, 25W	17c(B)	Hit	BD646F, BDT62F, 2SB1021..22, 2SB1224++
2SB1391	Si-P-Darl+Di	=2SB791: Iso, 25W	17c(B)	Hit	BD652F, BDT62CF, 2SB1259
2SB1392	Si-P	NF-L, 70V, 4A, 25W	17c	Hit	BD952F, 2SA1635, 2SB1017, 2SB1335, ++

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2SB1393(A)	Si-P	=2SB929(A): 25W	17c	Mat	BD936F, 2SB1015, 2SB1094, 2SB1375,++
2SB1394	Si-P+Di+R	Motor-Tr, 40V, A, Rb=90Ω, Rbe=800Ω	39b	Say	—
2SB1395	Si-P	Uni, lo-sat, 15V, 3A, 0,75W	7c	Say	2SB893, 2SB985, 2SB1117, 2SB1300, ++
2SB1396	Si-P	=2SB1395: SMD	39b		2SB1124, 2SB1301, 2SB1518
2SB1397	Si-P+Di+R	SMD, lo-sat, 25V, 2A, Rb=0Ω, Rbe=1,6kΩ	39b	Say	—
2SB1398	Si-P	=2SB1288=2SB1319: Pins=14mm	9c	Mat	→2SB1288
2SB1399	Si-P-Darl+Di	=2SB955: Iso, 30W	17c	Hit	BDT82CF, 2SB1259
2SB14	Ge-P	NF-V, ra, 30V, 0,05A, 0,05W	5g	Fui	AC125..126, AC151r, ACY32, 2SB173
2SB140	Ge-P	NF/S-L, 40V, 1,5A, 12W	23a	Son	AD149, 2N2136, 2N2143, 2SB449
2SB1400	Si-P-Darl+Di	=2SB727: Iso, 25W	17c	Hit	BD652F, 2SB1193, 2SB1340
2SB1401	Si-P-Darl+Di	NF-L, 300V, 0,3A, 15W, B>1000	17c	Hit	2SB1465, (2SB1061)
2SB1402	Si-P-Darl+Di	=2SB1105: Iso, 25W	17c	Hit	BDT60CF, 2SB1252, 2SB1340
2SB1403	Si-P-Darl+Di	=2SB1106: Iso, 25W	17c	Hit	BD652F, 2SB1193, 2SB1340
2SB1404	Si-P-Darl+Di	=2SB765: Iso, 25W	17c	Hit	BDT60CF, 2SB1252, 2SB1340
2SB1405	Si-P-Darl	80V, 0,7A, 1W, B>5000	9c	Say	2SB865, 2SB888, 2SB1129
2SB1406	Si-P-Darl	80V, 1,5A, 1W, B>4000	9c	Say	2SB865, 2SB1129
2SB1407L,S	Si-P	NF-L, 35V, 2,5A, 18W	30j	Hit	2SB906, 2SB962, 2SB1184, 2SB1202
2SB1409L,S	Si-P	NF-L, 180/160V, 1,5A, 18W, 240MHz	30j	Hit	2SA1552
2SB141	Ge-P	=2SB140: 80V	23a	Son	AD188..167, 2N2139, 2N2144
2SB1411	Si-P-Darl+Di	S-L, 100V, 3A, 20W, B=1,5k..15k	17c(B)	Tos	BDT60BF, 2SB1024, 2SB1226, 2SB1282,++
2SB1412(F5)	Si-P	30V, 5A, 120MHz	30c	Rhm	2SA1242, 2SA1795, 2SB967, 2SB1203,++
2SB1413	Si-P	NF-E, 45V, 1A, 1,5W, 200MHz	78b	Mat	2SB1142, (BD136, BD139, BD140,++)
2SB1414	Si-P	NF-E, 180/180V, 1A, 1,5W, 200MHz	78b	Mat	(2SA1249, 2SA1507, 2SB849)
2SB1415	Si-P-Darl+Di	int Z-Diode, 80V, 1A, 150MHz, B>4000	78b	Mat	—
2SB1416	Si-P	NF-E/S, 80V, 3A, 1,5W, 500/1500ns	78b	Mat	2SB1143, (BD178, BD180, BD190)
2SB1417	Si-P	NF-E/S, 80V, 3A, 15W, 30MHz	78c	Mat	BD936F, 2SA1488, 2SB1274, 2SB1375, ++
2SB1417A	Si-P	=2SB1417: 80V	78c		2SA1488A, 2SB1017, 2SB1335
2SB1418	Si-P-Darl+Di	NF-E/S, 80V, 2A, 15W, 20MHz, B>1000	78c	Mat	BDT80F, 2SB1223, 2SB1342, 2SB1411
2SB1418A	Si-P-Darl+Di	=2SB1418: 80V	78c		BDT60AF, 2SB1282, 2SB1342, 2SB1411
2SB1419	Si-P	NF-L, 180/180V, 12A, 120W	77j	Mat	2SA1301..1302, 2SB1162, 2SB1347
2SB142	Ge-P	NF/S-L, 30V, 1A, 10W, B>12	23a	Son	AD149, 2N2137, 2N2142, 2SB449
2SB1420	Si-P-Darl+Di	S-L, 120V, 18A, 80W, 50MHz, B>2000	18c(B)	Sak	BDV88B, D, BDW84D
2SB1421	Si-P	NF-L, 140/140V, 7A, 80W, 15MHz	18j	Mat	2SA1146, 2SA1186, 2SA1265, 2SA1491, ++
2SB1422	Si-P-Darl+Di	NF-L, int Z-Diode, 60V, 1A, 5W, B>4000	14h	Mat	(BD880, 2SB1034)
2SB1423	Si-P	=2SB1412:	14h	Rhm	2SA1120
2SB1424	Si-P	=2SB1428: SMD	39b	Rhm	2SA1730, 2SB1518
2SB1425	Si-P	lo-sat, 20V, 2A, 1W, 90MHz	7c(9mm)	Rhm	2SA1315, 2SB733, 2SB892, 2SB1434,++
2SB1426	Si-P	NF, lo-sat, 20V, 3A, 0,75W, 240MHz	7c	Rhm	2SB1117, 2SB1505
2SB1427	Si-P	hi-beta, -/20V, 2/3A, B=270..1200	39b	Rhm	2SA1369
2SB1428	Si-P	=2SB1426: 0,8W	9c	Rhm	2SB1117, 2SB1505
2SB1429	Si-P	HiFi-NF-E, 180V, 15A, 150W, 10MHz	77j	Tos	2SA1302, 2SA1553
2SB143(P)	Ge-P	=2SB142: B>23	23a	Son	AD149, 2N2137, 2N2142, 2SB449
2SB1430	Si-P-Darl+Di	NF/S-L, 100/100V, 5A, 20W, B>2000	17c	Nec	2SB1089, 2SB1227, 2SB1258, 2SB1340
2SB1431	Si-P-Darl+Di	NF/S-L, 100/100V, 8A, 25W, B>2000	17c	Nec	2SB1099, 2SB1228, 2SB1283, 2SB1344
2SB1432	Si-P-Darl+Di	NF/S-L, 100/100V, 10A, 30W, B>1000	17c	Nec	BDT62BF..CF, 2SB110, 2SB1259, 2SB1284
2SB1433	Si-P	NF-E, lo-sat, 50V, 2A, 0,9W	7c(9mm)	Hit	2SA1315, 2SB892, 2SB965
2SB1434	Si-P	NF-E, lo-sat, 50V, 2A, 1W, 110MHz	9c	Mat	2SA1706, 2SB892, 2SB1229
2SB1435	Si-P	=2SB1434: 1,5W, 80MHz	78b	Mat	(2SB966, 2SB1142)
2SB1436	Si-P	=2SB1412:	14b	Rhm	2SA1357
2SB1437	Si-P	NF-E, lo-sat, 100V, 1A, 1W, 120MHz	9c	Mat	2SA1706, (BC640, 2SB647, 2SB984)
2SB1438	Si-P	NF-E, lo-sat, 100V, 2A, 1W, 90MHz	9c	Mat	2SA1709
2SB1439	Si-P	=2SB1438: 1,5W, 200MHz	78b	Mat	—
2SB144(P)	Ge-P	=2SB142: B>45	23a	Son	AD149, 2N2137, 2N2142, 2SB449
2SB1440	Si-P	=2SB1434: SMD	39b	Mat	2SA1681, 2SB1123, 2SB1520
2SB1443	Si-P	=2SB1374:	9c	Rhm	→2SB1374
2SB1446	Si-P	Uni, 50V, 5A, 1W, 70MHz	9c	Mat	2SB1483
2SB1447	Si-P	NF, lo-sat, 50V, 3A, 1,5W, 250MHz	78b	Mat	2SB1143, (2SB986, 2SB1217)
2SB1448	Si-P-Darl	=2SB1265: Iso, 65W	18c	Shi	BDV88AF, (BDW84C, 2SB1285)
2SB1449	Si-P	S-L, lo-sat, 80V, 5A, 30W, 100/900ns	30c	Say	2SB1268, 2SB1270, 2SB1451
2SB145	Ge-P	=2SB142 gep, B=37	23a	Son	AD149, 2N2137, 2N2142, 2SB449
2SB1450	Si-P	S-L, lo-sat, 80V, 7A, 40W, 200/800ns	30c	Say	2SB1269, 2SB1271, 2SB1452
2SB1451	Si-P	S-L, lo-sat, 90V, 5A, 30W, 200/900ns	30c	Say	2SB1270..71, 2SB1452
2SB1452	Si-P	S-L, lo-sat, 90V, 7A, 40W, 200/900ns	30c	Say	2SB1271
2SB1453	Si-P	S-L, 80V, 3A, 5MHz, 400/2200ns	17c	Nec	BD936F, 2SB1015, 2SB1094, 2SB1375,++
2SB1454	Si-P	S-L, lo-sat, 90V, 5A, 25W, 20MHz	17c	Say	2SA1368, 2SA1441, 2SA1741, 2SB1018, ++
2SB1455	Si-P	S-L, lo-sat, 90V, 7A, 30W, 20MHz	17c	Say	2SA1442, 2SA1742, 2SB1018

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2SB1456	Si-P	NF, Io-sat, 150V, 1A, 1W, 120MHz	9c	Mat	—
2SB1457	Si-P-Darl+Di	NF/S, 100V, 2A, 0,9W, B>2000	7c	Tos	2SB1256, 2SB1387, 2SB1318
2SB1459	Si-P	=2SB1433: 80V	7c(9mm)	Hit	2SA1315, 2SB1438
2SB146	Ge-P	=2SB142: gep, B=75	23a	Son	AD149, 2N2137, 2N2142, 2SB449
2SB1460	Si-P	=2SB1425:	9c	Rhm	→2SB1425
2SB1461	Si-P	hi-beta, -/20V, 2/3A, B=270..1200	78b	Rhm	—
2SB1462	Si-P	SMD, Uni, 60V, 0,1A, 60MHz	35a(1,6mm)	Mat	2SA1832
2SB1463	Si-P	SMD, Uni, 150V, 0,05A, 200MHz	35a(1,6mm)	Mat	—
2SB1464	Si-P-Darl+Di	S-L, 60V, 8A, 25W, 20MHz, B>2000	17c	Mat	2SB1021..22, 2SB1224..25
2SB1465	Si-P-Darl	S-L, 300/300V, 0,3A, 25W, 25MHz, B>1500	17c	Nec	2SB1401
2SB1466	Si-P-Darl+Di	S-L, 100/100V, 15A, 100W, B>1000	18j	Hit	BDV66A..D, BDW84C..D, 2SB969
2SB1467	Si-P	S-L, 60V, 6A, 20W, 120MHz, 100/230ns	17c	Say	2SA1442, 2SA1470, 2SA1742
2SB1468	Si-P	S-L, 60V, 12A, 25W, 120MHz, 100/330ns	17c	Say	2SA1451..52, 2SA1568, 2SA1771
2SB1469	Si-P-Darl	L, 160/140V, 7A, 100W, 20MHz, B>5000	18j	Mat	2SB1493
2SB147	Ge-P	NF/S-L, 60V, 1,5A, 12W	23a	Son	AD168..167, 2N2139, 2N2144
2SB1470	Si-P-Darl	L, 160/160V, 6A, 150W, 20MHz, B>5000	77j	Mat	2SB1490, 2SD1503
2SB1471	Si-P-Darl	L, 70V, 6A, 30W, 500/2600ns, B>2000	30c(B)	Say	(BDW24B..C, BDW64B..D, 2SB1342, ++)-
2SB1472	Si-P-Darl	L, 70V, 7A, 35W, 500/2900ns, B>2000	30c(B)	Say	(BD648, BD900, BDW74B..D, 2SB1020, ++)
2SB1473	Si-P	=2SB987: Pins=14mm	9c	Mat	→2SB987
2SB1474(F5)	Si-P-Darl+Di	L, 80V, 4A, 10W, 12MHz, B>1000	30j	Rhm	2SB908, 2SB1072
2SB1475	Si-P	SMD, Uni, 25V, 0,5A, 50MHz	35a(2mm)	Nec	BC807W..808W, 2SB1219(A)
2SB1476	Si-P-Darl+Di	NF-L, 120/120V, 16A, 60W, B>2000	16c(B)	Sak	2SA1183, 2SB1557
2SB1477	Si-P	L, -/100V, 5A, 60W	16c	Rhm	2SA1671, (BD246D, 2SA1146, 2SA1186, ++)
2SB1478	Si-P-Darl+Di	L, -/100V, 6A, 60W, B>2000	16c	Rhm	BDV64C, BDV68B, BDW84D
2SB148	Ge-P	S-L, 80V, 15A, 40W		Tos	(2N1551..52, 2N1555..56, 2N1559..60, ++)
2SB1481	Si-P-Darl+Di	S-L, 100V, ±4A, 25W, 150/1200ns, B>2k	17c(B)	Tos	BDT60BF, 2SB1020, 2SB1024, 2SB1282, ++
2SB1482	Si-P	Blitzg./Strobo, -/20V, 5A, 1,2W	78b	Rhm	2SA1242, 2SB1288, 2SB1306, 2SB1446, ++
2SB1483	Si-P	Io-sat, 60/60V, 5A, 1W	9b	Nec	—
2SB1464	Si-P-Darl+Di	Uni, 100/100V, ±3A, 1W, B=2k..20k	9b	Nec	2SB1318
2SB1485M	Si-P	=2SB1374:	9c	Rhm	→2SB1374
2SB1468	Si-P	S, 400/400V, 0,5A, 1W, 25MHz	9c	Mat	2SA1625, 2SB1074
2SB1469	Si-P	S, 400/400V, 0,6A, 1,5W, 100MHz	78b	Mat	(2SA1156, 2SA1498)
2SB149	Ge-P	NF/S-L, 40V, 6A, 25W		Tos	AL100..101, 2N2288, 2N2291, ++
2SB1490	Si-P-Darl	S-L, 160/140V, 7A, 90W, 20MHz, B>5000	77j	Mat	2SB1470, 2SB1503
2SB1492	Si-P-Darl	L, 130/110V, 6A, 70W, 20MHz, B>5000	77j	Mat	2SB1470, 2SB1490, 2SB1503
2SB1493	Si-P-Darl	L, 160/140V, 7A, 70W, 20MHz, B>5000	18j	Mat	2SB1469, 2SB1560
2SB1494	Si-P-Darl+Di	S-L, 120/120V, 25A, 120W, B>2000	18j	Hit	2SB1383
2SB1495	Si-P-Darl+Di	S-L, 100V, 3A, 20W, 500/1400ns, B>2k	17c(B)	Tos	BDT60BF, 2SB1226, 2SB1250, 2SB1262, ++
2SB1496	Si-P	Uni, 60V, 3A, 1,6W, 15MHz	76c	Rhm	(BD178, BD190, 2SB1164, 2SB1202, ++)
2SB1497	Si-P	Uni, 60V, 3A, 1W, 50MHz, 150/600ns	9b	Nec	2SA1066, 2SA1707, 2SA1761
2SB1496	Si-P	S-L, 600/600V, 0,3A, 15W, <1/4µs	≈30c	Mat	—
2SB1499	Si-P	NF/S-L, 60V, 4A, 15W, 30MHz, 200/700ns	76c	Mat	(2SA1388, 2SA1469..70, 2SA1441)
2SB149A	Si-P	=2SA1499: 80V	76c		(2SA1388, 2SA1469..70, 2SA1441)
2SB149N	Ge-P	=2SA149: 60V, 7A			AL100..103, 2N2269, 2N2292, ++
2SB15	Ge-P	NF-V, 60V, 0,05A, 0,05W	5g	Fui	ACY24, ASY48, 2SB55
2SB150	Ge-P	S, 105V, 0,04A, 0,05W	2a	Tos	ACY39, 2N2042..2043
2SB1500	Si-P-Darl	L, 100/80V, 3A, 45W, 20MHz, B>5000	77j	Mat	2SB1492
2SB1501	Si-P-Darl	L, 110/90V, 4A, 50W, 20MHz, B>5000	77j	Mat	2SB1492
2SB1502	Si-P-Darl	L, 120/100V, 5A, 60W, 20MHz, B>5000	77j	Mat	2SB1492, 2SB1555..56
2SB1503	Si-P-Darl	L, 160/140V, 6A, 120W, 20MHz, B>5000	77j	Mat	2SB1470, 2SB1490
2SB1504	Si-P-Darl+Di	S-L, 50V, 6A, 20MHz, 500/3000ns, B>1000	78b	Mat	(BD646, BD898, BDW74A..D, 2SB1464, ++)
2SB1505	Si-P	Io-sat, 30V, 3A, 0,9W	7c(9mm)	Hit	2SB985, 2SB1117, 2SB1592
2SB1507	Si-P	S-L, 60V, 7A, 40W, 10MHz, 200/800ns	16c	Say	2SA1670, 2SB1371, (BD246A..F, ++)
2SB1508	Si-P	S-L, 60V, 12A, 45W, 10MHz, 100/500ns	16c	Say	(BD546A..D, 2SA1292, 2SB828..829, ++)
2SB1509	Si-P	S-L, 60V, 15A, 50W, 20MHz, 200/600ns	16c	Say	(BD546A..D, 2SA1292, 2SB828..829, ++)
2SB151	Ge-P	NF/S-L, 60V, 5A, 50W	23a	Fui	AL102..103, 2N3815, 2N3617, 2SB231, ++
2SB1510	Si-P-Darl	60V, 3A, B>2000, 1,5W	12b(B)	Say	(BUT60AF, 2SB1282, 2SB1342, 2SB1568, ++
2SB1511	Si-P	S-L, 60V, 20A, 40W, 120MHz, 300/320ns	16c	Say	(2SB904)
2SB1512	Si-P-Darl+Di	L, -/80V, 4A, 18W, B>1000	17c(B)	Rhm	2SB908, 2SB1072
2SB1513	Si-P-Darl+Di	L, -/120V, 6A, 18W, B>2000	76c	Rhm	—
2SB1514	Si-P-Darl+Di	L, -/100V, 8A, 18W, B>1000	17c(B)	Rhm	—
2SB1515	Si-P-Darl+Di	NF, 60V, 4A, 1,2W, 12MHz, B=5000	14b(B)	Rhm	2SB908, 2SB1072
2SB1516(F5)	Si-P	NF-L, 60V, 3A, 10W, 18MHz	80c	Rhm	2SB1215..16, (BD190, BD442, ++)
2SB1517	Si-P	NF-Tr, -/50V, 3A, 1,2W	78b	Rhm	2SA1761, 2SB908, 2SB985, 2SB1184, ++
2SB1518	Si-P	=2SB1505: SMD	39b	Hit	2SA1736, 2SB1124
2SB1519	Si-P	=2SB1433: SMD	39b	Hit	2SA1681, 2SB1123..24, 2SB1313

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2SB152(A)	Ge-P	=2SB151: 100V	23a	Fui	AL102..103, 2N3616, 2N3618, 2SB231,++
2SB1520	Si-P	=2SB1459: SMD	39b	Hit	2SB1572
2SB1522K	Si-P	SMD, Uni, 15V, 1A, 200MHz	35	Rhm	—
2SB1526	Si-P-Darl+Di	S-L, 60V, 2A, 20MHz, 0,4/2µs, B>1000	78b	Mat	(BD778, BD780, 2SB794..95, 2SB1067,++)
2SB1527	Si-P+Di	SMD, Rbe=1kΩ, 20V, 0,8A, 250MHz	35a	Say	—
2SB1529	Si-P	NF-L, 180/180V, 15A, 150W, 45MHz	77j	Mat	2SA1302, 2SB1163, 2SB1317, 2SB1429
2SB153	Ge-P	NF, 12V, 0,07A, 0,15W	2a	Hit	AC125..126, AC151, 2SB54, 2SB56
2SB1530	Si-P	NF-L, 200/150V, 2A, 20W	17c	Hit	2SA1306B, 2SA1668, 2SB1096
2SB1531	Si-P-Darl	NF/S-L, 130/110V, 8A, 50W, 20MHz	18j	Mat	2SB1469, 2SB1493, 2SB1557..58
2SB1532	Si-P	NF-L, 40V, 10A, 40W	17c	Fjd	2SA1327, 2SA1587, 2SA1599, 2SB948(A)
2SB1535(F5)	Si-P	NF-L, 100/100V, 8A, 10W, 18MHz	30c	Rhm	(BD244C..F, BD540C..D, BD954, 2SB633)
2SB1536	Si-P	Uni, 30V, 5A, 1,2W, 120MHz	≈12b	Mat	(2SA1307, 2SA1469, 2SA1643)
2SB1537	Si-P	SMD, Io-sat, 10V, 1A, 120MHz	39b	Mat	2SA1314, 2SA1734, 2SB1121
2SB1539	Si-P	SMD, Io-sat, 20V, 1A, 120MHz	39b	Mat	2SA1314, 2SA1734, 2SB1121
2SB154	Ge-P	NF, 12V, 0,07A, 0,15W	2a	Hit	AC125..126, AC151, 2SB54, 2SB56
2SB1541	Si-P	Uni, 60V, 1A, 1,2W, 150MHz	≈12b	Mat	(BD518, BD526, 2SA962, 2SB1201,++)
2SB1542	Si-P	Uni, 50V, 2A, 1,2W, 140MHz	≈12b	Mat	(BD510, BD516, 2SA1241, 2SB1201,++)
2SB1543	Si-P	Uni, 60V, 3A, 1,2W, 30MHz	≈12b	Mat	(2SA1876, 2SB906, 2SB1184, 2SB1202,++)
2SB1544	Si-P	Uni, 80V, 1A, 1,2W, 130MHz	≈12b	Mat	(BD520, BD528, BD530, 2SA1593,++)
2SB1545	Si-P	Uni, 150V, 1A, 1,2W, 110MHz	≈12b	Mat	(2SA1014, 2SA1225, 2SB905, 2SB1275,++)
2SB1546	Si-P	S, 400/400V, 0,5A, 1,2W, 25MHz	≈12b	Mat	(2SA1158, 2SA1498, 2SA1727 2SA1772)
2SB1548	Si-P	NF/S-L, 80V, 3A, 25W, 30MHz	17c	Mat	BDT32(A..C)F, 2SA1338, 2SA1441, 2SA1469
2SB1549	Si-P-Darl+Di	NF, 80V, 10A, 18W, 12MHz, B=7000	78c	Rhm	—
2SB155	Ge-P	NF-Tr/E, 16V, 0,3A, 0,15W	2a	Hit	AC126, AC153, AC188, 2SB405, 2SB475
2SB1550	Si-P-Darl+Di	=2SB1549: 40W	17j	Rhm	—
2SB1551	Si-P-Darl+Di	=2SB1549: 30W	17c	Rhm	—
2SB1553	Si-P	NF/S-L, hi-beta, 80V, 3A, 15W, 30MHz	78c	Mat	(2SB1299, 2SB1314)
2SB1554	Si-P	NF/S-L, hi-Ueb, 60V, 4A, 15W, 25MHz	78c	Mat	—
2SB1555	Si-P-Darl	NF/S-L, 140/140V, 7A, 100W, B>5000	77j	Tos	2SB1470, 2SB1490, 2SB1503
2SB1556	Si-P-Darl	NF/S-L, 140/140V, 8A, 120W, B>5000	77j	Tos	2SB1470, 2SB1490, 2SB1503
2SB1557	Si-P-Darl	=2SB1555: 70W	18j	Tos	2SB1469, 2SB1493
2SB1558	Si-P-Darl	=2SB1556: 60W	18j	Tos	2SB1580
2SB1559	Si-P-Darl	NF-L, 160/150V, 8A, 80W, 65MHz, B>5k	18j	Sak	(BDV66D)
2SB156(H)	Ge-P	NF-Tr/E, 16V, 0,3A, 0,15W	2a	Hit	AC126, AC153, AC188, 2SB405, 2SB475
2SB1560	Si-P-Darl	NF-L, 160/150V, 10A, 100W, 50MHz, B>5k	18j	Sak	(BDV66D)
2SB1561	Si-P	SMD, Io-sat, 80V, 2A, 150MHz	39b	Rhm	2SA1669, 2SB1123
2SB1562	Si-P	hi-beta, 80V, 3A, 25W, B=300..1000	17c	Tos	2SB1299, 2SB1314
2SB1565	Si-P	NF-L, 80V, 3A, 25W, 15MHz	17c	Rhm	BD936F, BDT32..F, 2SA1488A, 2SA1635,++
2SB1566	Si-P	NF-L, 60V, 3A, 25W, 60MHz	17c	Rhm	BD936F, BDT32..F, 2SB1187, 2SB1375,++
2SB1567	Si-P-Darl+Di	NF-L, 100V, 2A, 20W, B=1k..10k	17c	Rhm	2SB1226, 2SB1250, 2SB1411, 2SB1495,++
2SB1568	Si-P-Darl+Di	NF-L, 80V, 4A, 30W, 12MHz, B=1k..10k	17c	Rhm	BDT60..F, 2SB1024, 2SB1282, 2SB1342,++
2SB1569	Si-P	NF-L, 120V, 1,5A, 20W, 50MHz	17c	Rhm	2SA1332, 2SA1393, 2SB1186(A), 2SA1859(A)
2SB1569A	Si-P	=2SB1569: 160V	17c	Rhm	2SA1332, 2SB1186A, 2SA1606, 2SA1859A
2SB156A(AH)	Ge-P	=2SB156: 20V	2a		AC128, AC153, AC188, 2SB405, 2SB475
2SB157	Ge-P	Min, NF, 7V, 5mA, 0,01W, β=35	37a	Mat	OC57
2SB1570	Si-P-Darl	NF-L, 160/150V, 12A, 150W, 50MHz, B>5k	20j	Sak	—
2SB1571	Si-P	SMD, Io-sat, 50V, 5A, 150MHz, 265/400	39b	Nec	2SB1578
2SB1572	Si-P	SMD, Io-sat, 80V, 3A, 160MHz, 155/545	39b	Nec	—
2SB1573	Si-P	NF/S-L, 60V, 3A, 10W, 270MHz	30c	Mat	2SB906, 2SB1184, 2SB1202, 2SA1876
2SB1574	Si-P	NF/S-L, -150V, 2A, 10W, 150MHz	30c	Mat	2SB836, 2SB1184, 2SB1201, 2SB1241
2SB1575	Si-P	NF/S-L, -150V, 5A, 10W, 70MHz	30c	Mat	2SA1732, 2SB1204, 2SA1796, 2SA1877
2SB1578	Si-P	SMD, S, 80V, 5A, 600/600ns	39b	Nec	(2SB1571)
2SB158	Ge-P	=2SB157: β=55	37a	Mat	OC58
2SB1582	Si-P	SMD, Uni, 30V, 0,5A, 200MHz	35d	Mat	BC807R..808R, BCX17R..18R, 2SA1326,++
2SB1583	Si-P	SMD, Uni, 185V, 0,05A, 200MHz	35d	Mat	—
2SB1584	Si-P	SMD, Io-sat, 25V, 0,5A, 150MHz	35d	Mat	2SA1298
2SB1585	Si-P	SMD, Io-sat, 15V, 0,5A, 130MHz	35d	Mat	2SA1298
2SB1586	Si-P-Darl+Di	NF-L, 120/120V, 8A, 80W, 80MHz, B>2k	18c	Sak	2SB1253..1255, (2SB1469, 2SB1493)
2SB1587	Si-P-Darl+Di	NF-L, 160/150V, 12A, 70W, 65MHz, B>5k	18c	Sak	2SB1254..1255, (2SB1469, 2SB1493)
2SB1588	Si-P-Darl+Di	NF-L, 160/150V, 10A, 70W, 50MHz, B>5k	18c	Sak	2SB1255, (2SB1560)
2SB1589	Si-P	SMD, Io-sat, 10V, 1A, 190MHz	39b	Mat	BC869, BCX69, 2SA1734
2SB159	Ge-P	=2SB157: β=80	37a	Mat	OC59
2SB1592	Si-P	Uni, Io-sat, 30V, 3A, 150MHz	7c(9mm)	Mat	2SA1707, 2SB985, 2SB1117, 2SB1505
2SB1593	Si-P	NF-E, Io-sat, 29V, 3A, 200MHz	78b	Mat	2SA1359, 2SB1143
2SB1594	Si-P-Darl	L, 160/180V, 10A, 150W, 30MHz, B>3000	77j	Tos	—
2SB1595	Si-P	NF-Tr/E, -/32V, 2A, 0,9W	7c(9mm)	Rhm	2SA1315, 2SB892, 2SB1469

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2SB1596	Si-P	NF-Tr, -/160V, 1,5A, 0,9W	7c(9mm)	Rhm	2SA1770, 2SB1130A, 2SB1212, 2SB1236A
2SB16	Ge-P	NF, 16V, 0,6A, 1,8W	≈2b	Fui	(AD162, 2SB493)
2SB160	Ge-P	=2SB157: NF-E, B=75	37a	Mat	OC60
2SB1602	Si-P	hi-beta, 60V, 3A, 1,3W, B>800	12b	Tos	—
2SB1603	Si-P	NF/S-L, lo-sat, 40V, 4A, 25W, 150MHz	17c	Mat	2SA1388, 2SA1469..70, 2SA1441
2SB1603A	Si-P	=2SB1603: 50V	17c		2SA1388, 2SA1469..70, 2SA1441
2SB1604	Si-P	NF/S-L, lo-sat, 40V, 10A, 40W, 100MHz	17c	Mat	2SA1327, 2SA1567, 2SB948(A)
2SB1604A	Si-P	=2SB1604: 50V	17c		2SA1327, 2SA1567, 2SB948A
2SB1605	Si-P	NF/S-L, 50V, 3A, 35W, 30MHz, 500/1500ns	17c	Mat	2SB1185, 2SB1274, 2SB1314
2SB1605A	Si-P	=2SA1605: 60V	17c		2SA1440
2SB1606	Si-P	NF/S-L, lo-sat, 130V, 5A, 40W, 30MHz	17c	Mat	2SA1650, 2SB945
2SB1607	Si-P	NF/S-L, lo-sat, 130V, 7A, 40W, 30MHz	17c	Mat	2SA1651, 2SB946
2SB161	Ge-P	NF-E, 30V, 0,1A, 0,125W, B=50	2a	Nec	AC125..126, AC151..152, 2SB475
2SB1610	Si-P	SMD, lo-sat, 10V, 0,5A, 120MHz	35d	Mat	2SA1298, 2SA1753, 2SB1584..85
2SB1611	Si-P	SMD, lo-sat, 20V, 0,5A, 100MHz	35d	Mat	2SA1298, 2SA1753, 2SB1584
2SB1612	Si-P	SMD, lo-sat, 10V, 2A, 60MHz	39b	Mat	2SA1383, 2SA1314, 2SB1121
2SB1614	Si-P	SMD, lo-sat, 20V, 2A, 60MHz	39b	Mat	2SA1363, 2SA1314, 2SB1121
2SB1616	Si-P-Darl+Di	L, -/80V, 4A, 30W, B>1000	17c	Rhm	2SB1098, 2SB1227, 2SB1282
2SB1617	Si-P-Darl+Di	100V, 2A, 1,3W, 50MHz, B>2000	12b	Tos	(2SB1316)
2SB1618	Si-P	=2SB1610:	35a(2mm)	Mat	BC808W, 2SA1745, 2SB1219
2SB1619	Si-P	=2SB1611:	35a(2mm)	Mat	BC808W, 2SA1745, 2SB1219
2SB162	Ge-P	=2SB161: 0,18W	2a°	Nec	AC125..128, AC151..152, 2SB475
2SB1620	Si-P-Darl	L, 200/200V, 15A, 130W, 60MHz, B>5000	18j	Sak	—
2SB1621	Si-P-Darl	=2SB1620: 17A, 200W	20j	Sak	—
2SB1622	Si-P-Darl	=2SB1620: Iso, 85W	18c	Sak	—
2SB1624	Si-P-Darl	NF-L, 110/110V, 6A, 60W, 60MHz, B>5000	18j	Sak	2SB1469, 2SB1493, 2SB1557
2SB1625	Si-P-Darl	=2SB1624: Iso	18c	Sak	2SB1253..54, 2SD1567
2SB1626	Si-P-Darl	=2SB1624: Iso, 30W	17c	Sak	—
2SB1627	Si-P	SMD, lo-sat, 45V, 0,1A, 60MHz	35d	Mat	BC856, BC860, BCW69..70
2SB1628	Si-P	SMD, lo-sat, 20V, 3A, 320MHz, 70/150ns	39b	Nec	2SB1301, 2SC1518
2SB1629	Si-P	hi-beta, 60V, 3A, 40W, B=300..700	17c	Mat	2SB1299, 2SB1314, 2SB1562
2SB163	Ge-P	=2SB161: B=75	2a	Nec	AC125..128, AC151..152, 2SB475
2SB1631	Si-P	=2SB1629: 15W	78c	Mat	(2SB1299, 2SB1314, 2SB1562)
2SB1638	Si-P	S-L, lo-sat, 40V, 7A, 15W, 150MHz	≈30j	Mat	—
2SB1638A	Si-P	=2SB1638: 50V	≈30j		—
2SB164	Ge-P	=2SB163: 0,18W	2a°	Nec	AC125..128, AC151..152, 2SB475
2SB1640	Si-P	NF, 60V, 3A, 1,8W, 9MHz	15c	Tos	(BD796, 2SB986, 2SB1065, 2SB1217)
2SB1841	Si-P-Darl+Di	100V, 5A, 18W, B=1,5k..15k	15c	Tos	—
2SB1642	Si-P	NF-L, 60V, 4A, 25W, 9MHz	17c	Tos	2SA1307, 2SA1469, 2SB1134..1135
2SB1643	Si-P	hi-beta, 60V, 3A, 40W, B=300..700	30j	Mat	—
2SB1647	Si-P-Darl	NF-L, 150V, 15A, 130W, B>5000, 45MHz	18j	Sak	—
2SB1648	Si-P-Darl	=2SB1847: 17A	20j	Sak	—
2SB1849	Si-P-Darl	=2SB1647: Iso	20j	Sak	—
2SB165	Ge-P	=2SB161: B=100	2a	Nec	AC125..128, AC151..152, 2SB475
2SB186	Ge-P	=2SB165: 0,18W	2a°	Nec	AC125..126, AC151..152, 2SB475
2SB167	Ge-P	NF, 20V, 0,5A, 0,2W	2a	Fui	AC128, AC153, AC188, 2SB405, 2SB415
2SB168	Ge-P	NF, 9V, 0,1A, 0,15W, β=60	2a	Fui	AC125..126, AC151, 2SB54, 2SB56
2SB169	Ge-P	=2SB186: β=85	2a	Fui	AC125..128, AC151, 2SB54, 2SB56
2SB16A	Ge-P	=2SB16: 20V	≈2b		(AD162, 2SB493)
2SB17	Ge-P	NF, 32V, 0,6A, 1,8W	≈2b	Fui	(AD162, 2SB493)
2SB170	Ge-P	NF, 30V, 0,1A, 0,125W, β>20	2a	Mat	AC125..128, AC151, 2SB54, 2SB56
2SB171	Ge-P	=2SB170: β>40	2a	Mat	AC125..128, AC151, 2SB54, 2SB56
2SB172	Ge-P	NF, 32V, 0,125A, 0,125W	2a	Mat	AC125..128, AC151, 2SB54, 2SB56
2SB173	Ge-P	NF, ra, 30V, 0,1A, 0,125W	2a	Mat	AC125..126, AC151r, ACY32, 2SB175
2SB174	Ge-P	NF, 20V, 0,3A, 0,225W	1a	Mat	AC128, AC152..153, AC188, 2SB405
2SB175	Ge-P	NF, 30V, 0,1A, 0,125W	2a	Mat	AC125..128, AC151, 2SB54, 2SB56
2SB176	Ge-P	NF, 32V, 0,125A, 0,125W	2a	Mat	AC125..128, AC151, 2SB54, 2SB56
2SB177	Ge-P	NF, 60V, 0,125A, 0,125W	2a	Mat	ACY24, ASY48, 2SB56
2SB178(18)	Ge-P	NF, 20V, 0,3A, 0,225W	2a	Mat	AC128, AC152..153, AC186, 2SB405
2SB178A	Ge-P	=2SB178: 40V	2a		2N1189..90, 2SB405ST
2SB178B	Ge-P	=2SB178: 60V	2a		—
2SB179	Ge-P	NF, 25V, 0,05A, 0,08W	2a	Tos	AC125..126, AC151, 2SB54, 2SB56
2SB17A	Ge-P	=2SB17: 40V	≈2b		(2SB493)
2SB18	Ge-P	NF, 60V, 0,6A, 1,8W	≈2b	Fui	—
2SB180	Ge-P	NF, 40V, 0,5A, 5,5W	2a	Fui	2SB493, (AD162)
2SB160A	Ge-P	=2SB160: 12W	2a		—

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2SB181	Ge-P	=2SB180: 60V	2a	Fui	—
2SB181A	Ge-P	=2SB160: 60V, 12W	2a		—
2SB183	Ge-P	NF, 12V, 0,02A, 0,05W, β=55	37a	Hit	(AC125..126, AC151, 2SB54, 2SB56)
2SB184	Ge-P	=2SB183: B=100	37a	Hit	(AC125..126, AC151, 2SB54, 2SB56)
2SB185	Ge-P	NF, 25V, 0,15A, 0,2W, β>30	2a	Say	AC125..126, AC151, 2SB54, 2SB56
2SB186(A, B)	Ge-P	=2SB185: β>100	2a	Say	AC126, AC151, 2SB54, 2SB56
2SB187	Ge-P	NF, 25V, 0,15A, 0,2W	2a	Say	AC125..126, AC151, 2SB54, 2SB56
2SB188	Ge-P	NF, 25V, 0,15A, 0,2W	2a	Say	AC125..126, AC151, 2SB54, 2SB56
2SB188	Ge-P	NF-Tr/E, 25V, 0,25A, 0,25W	2a°	Tos	AC128K, AC153K, AC188K, 2SB475
2SB18A	Ge-P	=2SB18: 60V	=2b		—
2SB19	Ge-P	NF-L, 18V, 2,5A, 5,5W		Fui	(AD149, AUY19, 2N2137, 2N2142, ++)
2SB190	Ge-P	NF, 25V, 0,05A, 0,09W, β=150	2a	Oki	AC125..126, AC151, 2SB54, 2SB56
2SB191	Ge-P	=2SB190: β=70	2a	Oki	AC125..128, AC151, 2SB54, 2SB56
2SB192	Ge-P	=2SB190: β=35	2a	Oki	AC125..126, AC151, 2SB54, 2SB56
2SB193	Ge-P	=2SB190: 0,1A	2a	Oki	AC125..126, AC151, 2SB54, 2SB56
2SB194	Ge-P	=2SB190: 0,1A, β=70	2a	Oki	AC125..126, AC151, 2SB54, 2SB56
2SB195	Ge-P	=2SB190: 0,1A, β=35	2a	Oki	AC125..126, AC151, 2SB54, 2SB56
2SB196	Ge-P	NF/S-L, 30V, 0,5A, 0,5W	2a	Oki	2SB493, (AD162)
2SB197	Ge-P	=2SB196: 50V	2a	Oki	—
2SB196	Ge-P	=2SB196: 70V	2a	Oki	—
2SB199	Ge-P	NF, 12V, 0,3A, 0,25W	1a	Fui	AC128, AC152..153, AC188, 2SB475
2SB20	Ge-P	=2SB19: 32V		Fui	(AD149, AUY19, 2N2137, 2N2142, ++)
2SB200	Ge-P	NF-Tr/E, 32V, 0,4A, 0,25W	2a	Tos	AC128, AC153, AC188, 2SB415
2SB200A	Ge-P	=2SB200: 45V	2a		2SB405ST
2SB201	Ge-P	NF-Tr/E, 35V, 0,4A, 0,3W, B>37	2a	Tos	AC126, AC153, AC188, 2SB415
2SB202	Ge-P	=2SB201: B>70	2a	Tos	AC126, AC153, AC188, 2SB415
2SB203	Ge-P	NF/S-L, 40V, 20A, 80W	68a	Shi	—
2SB204	Ge-P	NF/S-L, 40V, 30A, 80W	68a	Shi	—
2SB205	Ge-P	NF/S-L, 60V, 20A, 80W	68a	Shi	—
2SB206	Ge-P	NF/S-L, 60V, 30A, 80W	68a	Shi	—
2SB207	Ge-P	NF/S-L, 100V, 20A, 80W	68a	Shi	—
2SB207A	Ge-P	=2SB207: 140V	68a		—
2SB208	Ge-P	NF/S-L, 100V, 30A, 80W	68a	Shi	—
2SB208A	Ge-P	=2SB208: 140V	68a		—
2SB209	Ge-P	NF/S-L, 40V, 20A, 80W	88a	Shi	—
2SB21	Ge-P	=2SB19: 60V		Fui	(AD186, AUY19, 2N2139, 2N2144, ++)
2SB210	Ge-P	NF/S-L, 40V, 30A, 80W	88a	Shi	—
2SB211	Ge-P	NF/S-L, 60V, 20A, 80W	68a	Shi	—
2SB212	Ge-P	NF/S-L, 60V, 30A, 60W	88a	Shi	—
2SB213	Ge-P	NF/S-L, 100V, 20A, 80W	68a	Shi	—
2SB213A	Ge-P	=2SB213: 140V	68a		—
2SB214	Ge-P	NF/S-L, 100V, 30A, 80W	88a	Shi	—
2SB214A	Ge-P	=2SB214: 140V	68a		—
2SB215	Ge-P	NF/S-L, 100V, 3A, 24W	23a	Say	AL102..103, 2N1542, 2N1547, 2SB231, ++
2SB216(A)	Ge-P	=2SB215: 60V	23a	Say	AD149, 2N1540, 2N1545, 2SB449, ++
2SB217	Ge-P	=2SB215: 25V	28a	Say	AD149, 2N1539, 2N1544, 2SB449, ++
2SB218	Ge-P	NF/S, 80V, 0,1A, 0,225W	2a(B=case)	Nec	ACY39, 2N2042..43
2SB219	Ge-P	NF-Tr/E, 30V, 0,2A, 0,225W, B>19	2a(B=case)	Nec	AC125..126, AC151, 2SB54, 2SB56
2SB219A	Ge-P	=2SB219: 0,5A	2a(B=case)		AC126, AC152..153, AC188, 2SB415
2SB22	Ge-P	NF-Tr/E, 25V, 0,2A, 0,3W	2a°	Say	AC128(K), AC151..153, AC188(K), 2SB405
2SB220	Ge-P	=2SB219: B>34	2a(B=case)	Nec	AC125..126, AC151, 2SB54, 2SB56
2SB220A	Ge-P	=2SB219: 0,5A, B>34	2a(B=case)		AC126, AC152..153, AC188, 2SB415
2SB221	Ge-P	=2SB219: B>53	2a(B=case)	Nec	AC125..126, AC151, 2SB54, 2SB56
2SB221A	Ge-P	=2SB219: 0,5A, B>53	2a(B=case)		AC126, AC152..153, AC188, 2SB415
2SB222	Ge-P	=2SB219: B>72	2a(B=case)	Nec	AC125..126, AC151, 2SB54, 2SB58
2SB222A	Ge-P	=2SB219: 0,5A, B>72	2a(B=case)		AC128, AC152..153, AC188, 2SB415
2SB223	Ge-P	=2SB219: B>99	2a(B=case)	Nec	AC125..126, AC151, 2SB54, 2SB56
2SB223A	Ge-P	=2SB219: 0,5A, B>99	2a(B=case)		AC128, AC152..153, AC188, 2SB415
2SB224	Ge-P	NF, 45V, 0,5A, 0,225W, B>19	2a(B=case)	Nec	2N1189..1190, 2SB405ST
2SB225	Ge-P	=2SB224: B>34	2a(B=case)	Nec	2N1189..1190, 2SB405ST
2SB226	Ge-P	=2SB224: B>53	2a(B=case)	Nec	2N1189..1190, 2SB405ST
2SB227	Ge-P	=2SB224: B>72	2a(B=case)	Nec	2N1189..1190, 2SB405ST
2SB228	Ge-P	NF/S-L, 60V, 5A, 50W	23a	Hit	AL102..103, 2N1541, 2N1546, 2SB231, ++
2SB229	Ge-P	=2SB228: 100V	23a	Hit	AL102..103, 2N1542, 2N1547, 2SB231, ++
2SB23	Ge-P	NF, 15V, 0,01A, 0,04W	2a	Say	AC125..128, AC151, 2SB54, 2SB56
2SB230	Ge-P	=2SB228: 120V	23a	Hit	AL102, 2N1543, 2N1548, 2SB231, ++

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2SB231	Ge-P	S-L, TV-HA, 120V, 6A, 25W	23a	Tos	AL102, AU110, AU210, 2N5324
2SB232	Ge-P	S-L, 130V, 6A, 54W, B>20	23a	Mat	AL102, AU110, AU210, 2N5324, 2SB231
2SB233	Ge-P	=2SB232: B>100	23a	Mat	AL102, AU110, AU210, 2N5324, 2SB231
2SB234	Ge-P	=2SB232: 180V, B>15	23a	Mat	AU107, AU113, AU213, 2N5324
2SB235	Ge-P	S-L, 80V, 15A, 60W	38a	Tos	2N1982, 2N2075, 2N2079, 2N2492..93, ++
2SB236	Ge-P	=2SB235: 80V	38a	Tos	2N1981, 2N2076, 2N2080, 2N2490..91, ++
2SB237	Ge-P	=2SB235: 36V	38a	Tos	2N1980, 2N2077, 2N2081, 2N2490..91, ++
2SB238	Ge-P	NF/S-L, 40V, 1A, 13W	2a	Nec	2SB493, (AD162)
2SB239	Ge-P	=2B238: 80V	2a	Nec	—
2SB239A	Ge-P	=2B238: 100V	2a		—
2SB24	Ge-P	NF, 15V, 0,015A, 0,1W	2a	Say	AC125..126, AC151, 2SB54, 2SB56
2SB240	Ge-P	NF/S-L, 40V, 1A, 13W	2a	Nec	2SB493, (AD162)
2SB241A	Ge-P	=2B240: 80V	2a		—
2SB241(N)	Ge-P	=2SB240: 80V	2a	Nec	—
2SB241A(AN	Ge-P	=2B241: 100V	2a		—
2SB242	Ge-P	NF/S-L, 30V, 1A, 13W	2a	Nec	2SB493, (AD162)
2SB242A	Ge-P	=2B242: 80V	2a		—
2SB243	Ge-P	NF/S-L, 30V, 1A, 13W	2a	Nec	2SB493, (AD162)
2SB243A	Ge-P	=2SB243: 80V	2a		—
2SB244	Ge-P	NF/S-L, 80V, 1A, 13W	2a	Nec	—
2SB245	Ge-P	NF/S-L, 80V, 1A, 13W	2a	Nec	—
2SB246	Ge-P	NF/S-L, 40V, 5A, 54W	23a	Nec	AL102..103, 2N1539, 2N1544, 2SB231, ++
2SB247	Ge-P	=2SB246: 80V	23a	Nec	AL102..103, 2N1540, 2N1545, 2SB231, ++
2SB248	Ge-P	NF/S-L, 40V, 5A, 54W	23a	Nec	AL102..103, 2N1539, 2N1544, 2SB231, ++
2SB248A	Ge-P	=2SB248: 80V	23a		AL102..103, 2N1540, 2N1545, 2SB231, ++
2SB249	Ge-P	NF/S-L, 80V, 5A, 54W	23a	Nec	AL102..103, 2N1541, 2N1546, 2SB231, ++
2SB25(N)	Ge-P	NF/S-L, 80V, 1,5A, 20W	23a	Tos	AD166, AUY19, 2N2139, 2N2144, ++
2SB250	Ge-P	NF/S-L, 30V, 5A, 54W	23a	Nec	AL102..103, 2N1539, 2N1544, 2SB231, ++
2SB250A	Ge-P	=2SB250: 80V	23a		AL102..103, 2N1540, 2N1545, 2SB231, ++
2SB251	Ge-P	NF/S-L, 30V, 5A, 54W	23a	Nec	AL102..103, 2N1539, 2N1544, 2SB231, ++
2SB251A	Ge-P	=2SB251: 80V	23a		AL102..103, 2N1540, 2N1545, 2SB231, ++
2SB252	Ge-P	NF/S-L, 80V, 5A, 54W	23a	Nec	AL102..103, 2N1541, 2N1546, 2SB231, ++
2SB252A	Ge-P	=2SB252: 120V	23a		AL102, 2N1543, 2N1548, 2SB231, ++
2SB253	Ge-P	NF/S-L, 80V, 5A, 54W	23a	Nec	AL102..103, 2N1541, 2N1546, 2SB231, ++
2SB253A	Ge-P	=2SB253: 120V	23a		AL102, 2N1543, 2N1548, 2SB231, ++
2SB254	Ge-P	NF/S-L, 35V, 1A, 12W	22a	Say	AD162, 2SB474, 2SB481
2SB255	Ge-P	NF/S-L, 35V, 1A, 12W	22a	Say	AD162, 2SB474, 2SB481
2SB256	Ge-P	NF/S-L, 25V, 1A, 12W	22a	Say	AD162, 2SB474, 2SB481
2SB257	Ge-P	NF, ra, 18V, 0,04A, 0,06W	2a	Tos	AC125..126, AC151r, ACY32, 2SB173
2SB258	Ge-P	S-L, 120V, 15A, 60W	38a	Tos	—
2SB259	Ge-P	=2SB258: 80V	38a	Tos	2N1982, 2N2075, 2N2079, 2N2492, ++
2SB26	Ge-P	NF/S-L, 32V, 1,5A, 20W	23a	Tos	AD149, AUY19, 2N2137, 2N2142, ++
2SB260	Ge-P	=2SB258: 50V	38a	Tos	2N1980, 2N2077, 2N2081, 2N2491, ++
2SB261	Ge-P	NF, 20V, 0,03A, 0,085W, β=45	37a	Fui	(AC125..126, AC151, 2SB54, 2SB56)
2SB262	Ge-P	=2SB261: β=90	37a	Fui	(AC125..126, AC151, 2SB54, 2SB56)
2SB263	Ge-P	NF, 20V, 0,15A, 0,2W	2a	Fui	AC125..126, AC151, 2SB54, 2SB56
2SB264	Ge-P	NF, ra, 30V, 0,05A, 0,07W	2a	Nec	AC125..126, AC151r, ACY32, 2SB173
2SB265	Ge-P	NF/S, 40V, 0,1A, 0,17W	2a	Tos	AC125..126, AC151, 2SB54, 2SB56
2SB266	Ge-P	NF, 25V, 0,15A, 0,15W, β=87	2a	old	AC125..126, AC151, 2SB54, 2SB56
2SB267	Ge-P	=2SB266: B=70	2a	old	AC125..126, AC151, 2SB54, 2SB56
2SB268	Ge-P	NF, 30V, 0,15A, 0,25W	1a	Hit	AC128, AC152..153, AC166, 2SB475
2SB269	Ge-P	NF, ra, 25V, 0,15A, 0,15W	2a	old	AC125..126, AC151r, ACY32, 2SB173
2SB26A	Ge-P	=2SB26: 60V	23a		AD166, AUY19, 2N2139, 2N2144, ++
2SB27	Ge-P	NF/S-L, 15V, 0,5A, 5W, B>18	23a	Son	AD149, AUY19, 2N2137, 2N2142, 2SB449++
2SB270	Ge-P	NF, 12V, 0,15W	2a	Say	AC125..126, AC151, 2SB54, 2SB56
2SB271	Ge-P	NF, 25V, 0,5A, 0,72W, B=80	2a	Say	AC128, AC153, AC166, 2SB405, 2SB415
2SB272	Ge-P	=2SB271: B=100	2a	Say	AC126, AC153, AC188, 2SB405, 2SB415
2SB273	Ge-P	=2SB271: 35V, B=100	2a	Say	AC126, AC153, AC188, 2SB405, 2SB415
2SB274	Ge-P	NF/S-L, 80V, 6A, 50W	23a	Hit	AL102..103, 2N3615, 2N3617, 2N2526, ++
2SB275	Ge-P	=2SB274: 120V	23a	Hit	AL102, 2N2290, 2N2293, 2N2527, ++
2SB276	Ge-P	=2SB274: 120V, 10A	23a	Hit	AL100, 2N2290, 2N2293, 2N2527, ++
2SB277	Ge-P	NF, 15V, 5mA, 0,08W	1a	Mat	AC125..126, AC151, 2SB54, 2SB56
2SB278	Si-P	NF, hi-Ueb, 25V, 0,05A, 0,25W, β=28	1a	Mat	2SA1252, 2SB902, (BC558, ++)
2SB279	Si-P	=2SB278: β=50	1a	Mat	2SA1252, 2SB902, (BC558, ++)
2SB28	Ge-P	=2B27: B>35	23a	Son	AD149, AUY19, 2N2137, 2N2142, 2SB449++
2SB280	Si-P	NF, 32V, 0,25A, 0,3W	1a	Mat	BC213, BC256, BC308, BC558, 2SA953++

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2SB281	Si-P	=2SB280: 80V	1a	Mat	BC212, BC256, BC266, BC556, 2SA953++
2SB282	Ge-P	NF/S-L, 80V, 6A, 30W, B>15	23a	Mat	AL102..103, AUY22, 2N3615, 2N3617, ++
2SB283	Ge-P	=2SB282: 80V, B>35	23a	Mat	AL102..103, AUY21, 2N3612, 2N3614, ++
2SB284	Ge-P	=2SB282: 60V, B>20	23a	Mat	AL102..103, AUY21, 2N3612, 2N3614, ++
2SB285	Ge-P	=2SB282: B>20	23a	Mat	AL102..103, AUY22, 2N3615, 2N3617, ++
2SB266	Ge-P	NF/S-L, 80V, 6A, 43W, B=17	23a	Mat	AL102..103, AUY22, 2N3615, 2N3617, ++
2SB287	Ge-P	=2SB286: B=36	23a	Mat	AL102..103, AUY22, 2N3615, 2N3617, ++
2SB288	Ge-P	NF, 32V, 0,125A, 0,125W	2a	Mat	AC125..126, AC151..152, 2SB475
2SB289	Ge-P	=2SB288: 80V	2a	Mat	ACY24, ASY48, ASY77, 2SB55
2SB29	Ge-P	=2B27: B>72	23a	Son	AD149, AUY19, 2N2137, 2N2142, 26B449++
2SB290	Ge-P	NF, ra, 18V, 0,04A, 0,065W	2a	Tos	AC125..126, AC151r, ACY32, 2SB173
2SB291	Ge-P	NF, 30V, 0,15A, 0,15W	2a	Tos	AC125..126, AC151, 2SB54, 2SB56
2SB292	Ge-P	NF, 30V, 0,15A, 0,15W	2a	Tos	AC125..126, AC151, 2SB54, 2SB56
2SB292A	Ge-P	=2SB292: 60V	2a		ACY24, ASY48, ASY77, 2SB55
2SB293	Ge-P	NF, 18, 0,25A, 0,15W, B=70	2a	old	AC128, AC152..153, AC188, 2SB475
2SB294	Ge-P	=2SB293: β=36	2a	old	AC128, AC152..153, AC188, 2SB475
2SB295	Ge-P	NF/S-L, 100V, 5A, 40W	23a	Fui	AL102..103, 2N3616, 2N3618, 2N2527, ++
2SB296	Ge-P	S-L, TV-HA, 130V, 10A, 35W	23a	Toa	AU110, AU210
2SB299	Ge-P	NF/S, 30V, Ueb=25V, 0,15A, 0,15W	2a	old	AC125..126, AC151, ASY26, ASY76..77
2SB30	Ge-P	=2B27: gep., B=68	23a	Son	AD149, AUY19, 2N2137, 2N2142, 2SB449++
2SB300	Ge-P	NF/S-L, 100V, 10A, 36W	23a	Tos	AL100..101, 2N2290, 2N2293, 2N2527, ++
2SB301	Ge-P	=2SB300: 80V	23a	Tos	AL100..101, 2N2289, 2N2292, 2N2526, ++
2SB302	Ge-P	NF, ra, 10V, 2mA, 0,04A	2a	Hit	AC125..126, AC151r, ACY32, 2SB173
2SB303	Ge-P	NF, ra, 25V, 0,02A, 0,1W	2a	Say	AC125..126, AC151r, ACY32, 2SB173
2SB304	Ge-P	NF/S, 30V, 0,5A, 0,225W	2a	Fui	AC128, AC153, AC188, 2SB324, 2SB415
2SB304A	Ge-P	=2SB304: 45V	2a		ACY24, ASY48, ASY76..77, 2N1189..90
2SB305				Fui	—
2SB306	Ge-P	NF/S, 105V, 0,02A, 0,075W	2a	Tos	ACY39, 2N2042..2043
2SB309(A)	Ge-P	NF/S-L, 75V, 8A, 43W	23a	Mat	AL100..101, 2N2289, 2N2292, 2N2526, ++
2SB31	Ge-P	=2B27: gep., B=115	23a	Son	AD149, AUY19, 2N2137, 2N2142, 2SB449++
2SB310	Ge-P	=2SB309: 140V	23a	Mat	AU110, AU210, 2N2528
2SB311	Ge-P	=2SB309: 180V, 10A	23a	Mat	AU107, AU113, AU213, 2N5324
2SB312	Ge-P	=2SB309: 140V	23a	Mat	AU110, AU210, 2N2528
2SB313	Ge-P	=2SB309: 180V, 10A	23a	Mat	AU107, AU113, AU213, 2N5324
2SB314	Ge-P	NF/S, 30V, 0,5A, 3W	=2b*	Oki	2SB493, (AD162)
2SB315	Ge-P	NF, 16V, 0,3A, 0,15W, β=50	2a	Mit	AC126, AC152..153, AC188, 2SB475
2SB316	Ge-P	=2SB315: B=80	2a	Mit	AC126, AC152..153, AC188, 2SB475
2SB317	Ge-P	=2SB315: 0,25W, B=60	1a	Mit	AC128, AC152..153, AC188, 2SB475
2SB318	Ge-P	NF/S-L, 80V, 5A, 50W	23a	Fui	AL102..103, 2N1540, 2N1545, 2N2526, ++
2SB319	Ge-P	=2SB318: 100V	23a	Fui	AL102..103, 2N1542, 2N1547, 2N2527, ++
2SB32	Ge-P	NF, 20V, 0,05A, 0,15W	2a	Fui	AC125..128, AC151, 2SB54, 2SB56
2SB320	Ge-P	=2SB318: 100V, 10A	23a	Fui	AL100..101, 2N2290, 2N2293, 2N2527, ++
2SB321	Ge-P	=2SB322: ra, β=100	37a	Tos	(AC125..126, AC151r, ACY32, 2SB173)
2SB322	Ge-P	Min, NF, 12V, 0,05A, 0,04W, β=50	37a	Tos	(AC125..126, AC151, 2SB54, 2SB56)
2SB323	Ge-P	=2SB322: β=100	37a	Tos	(AC125..126, AC151, 2SB54, 2SB56)
2SB324	Ge-P	NF, 32V, 1A, 0,22W	2a	Mat	AC128, AC153, AC188, 2SB415
2SB325	Ge-P	S-L, 120V, 0,6A, 1,8W	≈2a	Fui	—
2SB326	Ge-P	NF/S, 30V, Ueb=15V, 0,5A, 0,225W, B>45	2a(B=case)	Nec	AC128, AC153, AC188, ASY78..77
2SB327	Ge-P	=2SB326: B>70	2a(B=case)	Nec	AC128, AC153, AC188, ASY78..77
2SB326	Ge-P	NF/S, 25V, 0,2A, 0,15W, B>40	2a	Nec	AC125..126, AC151..152, ASY26..27
2SB329	Ge-P	=2SB328: B>85	2a	Nec	AC125..126, AC151..152, ASY26..27
2SB33	Ge-P	NF, 20V, 0,05A, 0,15W	2a	Fui	AC125..126, AC151, 2SB54, 2SB56
2SB330	Ge-P	NF/S, 110V, 0,15A, 0,225W	2a(B=case)	Nec	ACY39, 2N2042..2043
2SB331(H)	Ge-P	S-L, 40V, 15A, 80W	38a	Hit	2N1980, 2N2078, 2N2082, 2N2491, ++
2SB332(H)	Ge-P	=2SB331: 80V	38a	Hit	2N1981, 2N2076, 2N2080, 2N2491, ++
2SB333(H)	Ge-P	=2SB331: 80V	38a	Hit	2N1982, 2N2075, 2N2079, 2N2492, ++
2SB334(H)	Ge-P	=2SB331: 100V	36a	Hit	2N2493
2SB335	Ge-P	Min, NF, 20V, 0,06A, 0,063W, B=80	37a	Mat	(AC125..126, AC151, 2SB54, 2SB58)
2SB336	Ge-P	=2SB335: B=120	37a	Mat	(AC125..126, AC151, 2SB54, 2SB58)
2SB337(H)	Ge-P	NF/S-L, 40V, 7A, 30W	23a	Hit	AL102..103, AUY22, 2N3611, 2N3613, ++
2SB338(H)	Ge-P	=2SB337: 80V	23a	Hit	AL102..103, AUY22, 2N3612, 2N3614, ++
2SB339(H)	Ge-P	NF/S-L, 80V, 10A, 44W	23a	Hit	AL100..101, 2N2289, 2N2292, 2N2526, ++
2SB34	Ge-P	NF, 20V, 0,15A, 0,25W	1a	Fui	AC125..126, AC151, 2SB54, 2SB56
2SB340(H)	Ge-P	=2SB339: 100V	23a	Hit	AL100..101, 2N2290, 2N2293, 2N2527, ++
2SB341(H)	Ge-P	=2SB339: 120V	23a	Hit	AL100..101, 2N2290, 2N2293, 2N2527, ++
2SB342	Ge-P	NF/S-L, 120V, 6A, 30W	23a	Say	AU110, AU210, 2N2527..2528

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2SB343	Ge-P	=2SB342: 150V	23a		AU107, AU110, 2N2528
2SB345	Ge-P	NF, 32V, 0,1A, 0,165W, 065	2a	Mal	AC125..126, AC151, 2SB54, 2SB56
2SB346	Ge-P	=2SB345: β>80	2a	Mal	AC125..126, AC151, 2SB54, 2SB56
2SB347	Ge-P	=2SB345: ra	2a	Mal	AC125..126, AC151r, ACY32, 2SB173
2SB348	Ge-P	=2SB345: ra, β>80	2a	Mal	AC125..126, AC151r, ACY32, 2SB173
2SB349	Ge-P	NF, 20V, 0,01A, 0,05W	2a	Say	AC125..126, AC151, 2SB54, 2SB56
2SB350	Ge-P	NF, 25V, 0,05A, 0,15W	2a	Say	AC125..126, AC151, 2SB54, 2SB56
2SB351	Ge-P	S-L, 40V, 15A, 70W	38a	Fui	2N1980, 2N2076, 2N2062, 2N2491
2SB352	Ge-P	=2SB351: 80V	38a	Fui	2N1981, 2N2076, 2N2080, 2N2492
2SB353	Ge-P	=2SB351: 80V	38a	Fui	2N1982, 2N2075, 2N2079, 2N2492
2SB354	Ge-P	=2SB351: 100V	36a	Fui	2N2493
2SB355	Ge-P	NF/S-L, 25V, 1A, 15W	22a	Hit	AD162, 2SB474, 2SB481
2SB356	Ge-P	=2SB355: 60V	22a	Hit	—
2SB357	Ge-P	=2SB355: 100V	22a	Hit	—
2SB356	Ge-P	NF/S-L, 80V, 6A, 50W	23a	Hit	AL102..103, 2N3615, 2N3617, 2N2526, ++
2SB359	Ge-P	=2SB356: 120V, 10A	23a	Hit	AL100, 2N2290, 2N2293, 2N2527, ++
2SB360	Ge-P	=26B356: 160V, 10A	23a	Hit	AU107, AU113, AU213, 2N5324
2SB361(H)	Ge-P	NF/S-L, 80V, 5A, 40W	23a	Hit	AL102..103, AUY22, 2N1541, 2N1546, ++
2SB362(H)	Ge-P	NF/S-L, 100V, 7A, 50W	23a	Hit	AL102..103, 2N3616, 2N3616, 2N2527, ++
2SB363	Ge-P	NF/S-L, 140V, 8A, 43W	23a	Nec	AU107, AU110, AU210, 2N2526
2SB364	Ge-P	NF, 20V, 0,4A, 0,15W, B>60	2a	Tos	AC128, AC153, AC188, 2SB475
2SB365	Ge-P	=2SB364: B>35	2a	Tis	AC128, AC153, AC188, 2SB475
2SB366	Ge-P	NF/S-L, 140V, 8A, 43W	23a	Tos	AU107, AU110, AU210, 2N2526
2SB367(H)	Ge-P	NF-L, 25V, 1A, 6,6W	22a	Hit	AD162, 2SB474, 2SB461
2SB366(H)	Ge-P	=2SB367: 45V	22a	Hit	—
2SB37	Ge-P	NF, 30V, 0,05A, 0,15W	2a	Fui	AC125..126, AC151, 2SB54, 2SB56
2SB370(H)	Ge-P	NF, 25V, 0,5A, 0,2W	2a	Hit	AC126, AC153, AC166, 2SB405, 2SB475
2SB370A(AH)	Ge-P	=2SB370: 32V	2a	Hit	AC126, AC153, 2SB415, 2SB475
2SB371	Ge-P	NF, 32V, 0,2A, 0,165W	2a	Mal	AC125..126, AC151..152, 2SB475
2SB372	Ge-P	NF, 25V, 1A, 1,5W, B=70	2a	Say	AC128, AC153, AC188, 2SB405, 2SB415
2SB373	Ge-P	=2SB372: B=150	2a	Say	AC126, AC153, AC188, 2SB405, 2SB415
2SB374	Ge-P	=2SB372: 60V, B=150	2a	Say	2N1039, 2N2565
2SB375(A)	Ge-P	S-L, 150V, 9A, 30W	23a	Say	AU107, AU110, AU113, AU213, 2N5324
2SB376	Ge-P	NF, 20V, 0,3A, 0,225W	2a	Mal	AC126, AC152..153, AC188, 2SB475
2SB377	Ge-P	NF, ra, 32V, 0,15A, 0,27W	2a(B=case)	Son	AC125..126, AC151r, ACY32, 2SB173
2SB376	Ge-P	NF, 16V, 0,15A, 0,16W	2a(B=case)	Son	AC126, AC152..153, AC166, 2SB475
2SB379A, B	Ge-P	=2SB376: 23V, 0,3..0,5A, 0,27W	2a(B=case)	Son	AC126, AC152..153, AC166, 2SB475
2SB379	Ge-P	NF, 16V, 0,15A, 0,18W	2a(B=case)	Son	AC126, AC152..153, AC188, 2SB475
2SB379A, B	Ge-P	=2SB379: 23V, 0,3..0,5A, 0,27W	2a(B=case)	Son	AC126, AC152..153, AC188, 2SB475
2SB36	Ge-P	NF, 30V, 0,15A, 0,25W	1a	Fui	AC125..126, AC151, 2SB54, 2SB56
2SB380	Ge-P	NF, 16V, 0,15A, 0,16W	2a(B=case)	Son	AC126, AC152..153, AC188, 2SB475
2SB380A, B	Ge-P	=2SB360: 23V, 0,3..0,5A, 0,27W	2a(B=case)	Son	AC128, AC152..153, AC188, 2SB475
2SB361	Ge-P	NF, 32V, 0,3A, 0,27W	2a(B=case)	Son	AC126, AC152..153, AC188, 2SB475
2SB382	Ge-P	NF, 32V, 0,3A, 0,27W	2a(B=case)	Son	AC128, AC152..153, AC188, 2SB475
2SB383	Ge-P	NF, 32V, 0,5A, 0,27W	2a(B=case)	Son	AC126, AC152..153, AC188, 2SB475
2SB384	Ge-P	NF, 20V, 0,03A, 0,06W, β=60	2a	old	AC125..126, AC151, 2SB54, 2SB56
2SB385	Ge-P	=2SB384: B=50	2a	old	AC125..126, AC151, 2SB54, 2SB56
2SB386	Ge-P	NF/S, 30V, 0,3A, 0,15W	2a	Hit	AC126, AC152..153, AC188, ASY26
2SB387	Ge-P	Min, NF, 12V, 0,02A, 0,03W	37e	Hit	(AC125..126, AC151, 2SB54, 2SB56)
2SB369	Ge-P	NF, ra, 12V, 0,01A, 0,06W	2a	Fui	AC125..126, AC151r, ACY32, 2SB173
2SB38	Ge-P	NF, ra, 10V, 2mA, 0,05W	2a	Fui	AC125..126, AC151r, ACY32, 2SB173
2SB390	Ge-P	NF/S-L, 80V, 6A, 30W	23a	Say	AL102..103, AUY22, 2N3615, 2N3817, ++
2SB391	Ge-P	=2SB390: 50V	23a	Say	AL102..103, AUY22, 2N3812, 2N3614, ++
2SB392	Ge-P	NF/S, 20V, 0,2A, 0,2W	2a	Oki	AC125..126, AC151..152, ASY26..27
2SB383	Ge-P	NF/S, 28V, 0,2A, 0,2W	2a	Oki	AC125..126, AC151..152, ASY26..27
2SB394	Ge-P	NF/S, 28V, 0,2A, 0,2W	2a	Oki	AC125..126, AC151..152, ASY26..27
2SB395	Ge-P	NF/S, 26V, 0,2A, 0,2W	2a	Oki	AC125..126, AC151..152, ASY26..27
2SB396	Ge-P	NF/S, 40V, 0,2A, 0,15W	2a	Oki	ASY48, ASY76..77, 2N1191..94
2SB397	Ge-P	NF/S, 48V, 0,08A, 0,2W	2a	Oki	ASY48, ASY77, 2N1191..94
2SB396	Ge-P	NF/S, 110V, 0,08A, 0,2W	2a	Oki	ACY39, 2N2042..2043
2SB399	Ge-P	NF/S, 110V, 0,08A, 0,2W	2a	Oki	ACY39, 2N2042..2043
2SB40	Ge-P	NF/S, 40V, 0,1A, 0,06W	2a	Tos	ASY46, ASY76..77, 2SB177
2SB400	Ge-P	NF, ra, 20V, 0,04A, 0,1W	2a	Say	AC125..126, AC151r, ACY32, 2SB173
2SB401	Ge-P	NF/S, 40V, 0,3A, 0,24W	2a	Mal	ACY24, ASY48, ASY76..77
2SB402	Ge-P	=2SB401: 60V	2a		ACY24, ASY48, ASY77
2SB403	Ge-P	NF/S, 40V, 0,3A, 0,24W	2a	Mal	ACY24, ASY48, ASY76..77

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2SB404	Ge-P	NF/S, 100V, 0,1A, 0,1W	2a	Say	ACY39, 2N2042..43
2SB405	Ge-P	NF, 30V, 1A, 0,21W	3a	Say	AC128, AC153, AC188, 2SB415
2SB405K	Ge-P	=2SB405:	3a		AC128K, AC153K, AC188K
2SB405ST	Ge-P	=2SB405: 40V	3a		—
2SB406	Ge-P	S-L, 200/100V, 10A, 37,5W	23a	Say	AU107, AU113, AU213, 2N5324
2SB407	Ge-P	NF/S-L, 30V, 7A, 30W	23a	Say	AL102..AL103, AUY22, 2N3611, 2N3613++
2SB408	Ge-P	NF, 25V, 0,2A, 0,3W	2a	Say	AC125..128, AC151, 2SB54, 2SB56
2SB409	Ge-P	NF, 12V, 0,08A, 0,15W	2a	Say	AC125..128, AC151, 2SB54, 28B56
2SB41	Ge-P	NF/S-L, 40V, 1,2A, 44W	23a	Fui	AD149, AUY19, 2N2136, 2N2143, 2SB449++
2SB410	Ge-P	S-L, TV-HA, 135V, 15A, 40W	23a	Say	AU107, AU110, AU210
2SB411	Ge-P	S-L, TV-HA, 200V, 11A, 40W	23a	Say	AU107, AU113, AU213, 2N5324
2SB412	Ge-P	S-L, TV-HA, 300V, 11A, 40W	23a	Say	AU106, AU109, AU111, AU112, 2N5325
2SB413	Ge-P	NF/S-L, 60V, 1,5A, 12,5W	22a	Tos	—
2SB414	Ge-P	=2SB413: 32V	22a	Tos	AD162, 2SB474, 2SB461
2SB415	Ge-P	NF, 32V, 1A, 0,2W	2a	Tos	AC128, AC153, AC188, 2SB324
2SB416	Ge-P	NF, 25V, 0,08A, 0,15W	2a	Oki	AC125..126, AC151, 2SB54, 28B56
2SB417	Ge-P	=2SB416: 45V	2a	Oki	ACY24, ASY48, ASY77, 2N1191..94
2SB416	Ge-P	=2SB416: 70V	2a	Oki	ACY24, ASY48, ASY77, 2N2042..43
2SB419(H)	Ge-P	NF/S-L, 45V, 1,5A, 6W	22a	Hit	—
2SB42	Ge-P	=2SB41: 60V	23a	Fui	AD188, AUY19, 2N2139, 2N2144, ++
2SB420	Ge-P	NF/S-L, 120V, 1,5A, 6W	22a	Hit	—
2SB421	Ge-P	NF/S, 60V, 0,6A, 0,3W	2a	Tos	ACY39, 2N2042..2043
2SB422	Ge-P	NF, 18V, 0,04A, 0,06W	2a	Tos	AC125..126, AC151, 2SB54, 2SB56
2SB423	Ge-P	NF, 30V, 0,15A, 0,15W	2a	Tos	AC125..128, AC151, 2SB54, 2SB56
2SB424	Ge-P	NF/S-L, 60V, 3A, 30W	23a	Tos	AUY20, 2N1541, 2N1548, 2N2141, 2N2146++
2SB425	Ge-P	=2SB424: 60V	23a	Tos	AUY19, 2N1540, 2N1545, 2N2139, 2N2144++
2SB426	Ge-P	NF/S-L, 32V, 3A, 30W	23a	Tos	AUY19, 2N1539, 2N1544, 2N2137, 2N2142++
2SB426A	Ge-P	=2SB428: 45V	23a	Tos	AUY19, 2N1539, 2N1544, 2N2136, 2N2143++
2SB427	Ge-P	NF/S, 45V, 0,5A, 0,225A, B=60	2a	Fui	2N1189..90, 2SB405ST
2SB426	Ge-P	=2SB427: B=90	2a	Fui	2N1189..90, 2SB405ST
2SB429	Ge-P	NF, 30V, 0,05A, 0,1W	2a	Nec	AC125..128, AC151, 2SB54, 2SB56
2SB43	Ge-P	NF, 25V, 0,05A, 0,15W	2a	Tos	AC125..128, AC151, 2SB54, 2SB56
2SB430	Ge-P	S-L, 70V, 20A, 80W	38a	Mat	2N1519, 2N1521, 2N1523
2SB431	Ge-P	NF, 32V, 0,5A, 0,2W	2a	Fui	AC128, AC153, AC188, 2SB324, 2SB415
2SB432	Ge-P	NF/S-L, 150V, 5A, 50W	23a	Fui	AU107, AU110, 2N2528
2SB433(F)	Ge-P	NF/S-L, 70V, 15A, 56W	38a	Fui	2N1981, 2N2076, 2N2080, 2N2490
2SB434	Si-P	NF-L, 50V, 3A, 25W, 10MHz	17j	Tos,Mic	BD242, BD540A, BD536, BD936, ++
2SB435	Si-P	=2SB434: 40V	17j	Tos,Mic	BD242, BD540, BD534, BD934, ++
2SB436	Ge-P	NF, 25V, 0,12A, 0,12W	2a	Oki	AC125..128, AC151, 2SB54, 2SB56
2SB437	Ge-P	=2SB436: 45V	2a	Oki	ACY24, ASY48, ASY76..77, 2N1191..94
2SB436	Ge-P	=2SB436: 70V	2a	Oki	ACY24, ASY48, ASY76..77
2SB439	Ge-P	NF, ra, 30V, 0,15A, 0,15W	2a	Tos	AC125..128, AC151r, ACY32, 2SB173
2SB43A	Ge-P	=2SA43: 45V, 0,15A	2a		ACY24, ASY48, 2SB55, 2SB56A
2SB44	Ge-P	NF, 30V, 0,05A, 0,08W	2a	Tos	AC125..128, AC151, 2SB54, 2SB56
2SB440	Ge-P	NF, ra, 30V, 0,15A, 0,15W	2a	Tos	AC125..128, AC151r, ACY32, 2SB173
2SB441	Ge-P	S-L, 160/45V, 5A, 40W	23a	Hit	AU107, AU110, 2N2528
2SB442(H)	Ge-P	S-L, 160/60(H=/80)V, 6A, 40W	23a	Hit	AU107, AU110, 2N2528
2SB443	Ge-P	NF, ra, 18V, 0,01A, 0,1W	2a	Hit	AC125..128, AC151r, ACY32, 2SB173
2SB444	Ge-P	NF, ra, 18V, 0,01A, 0,1W	2a	Hit	AC125..128, AC151r, ACY32, 2SB173
2SB445	Ge-P	NF/S-L, 40V, 1,5A, 10W	22a	Fui	AD162, 28B474, 2SB481
2SB446	Ge-P	=2SB445: 60V	22a		—
2SB447	Ge-P	S-L, 220V, 6A, 45W	23a	Fui	AU113, AU213, 2N5324
2SB448	Ge-P	NF/S-L, 32V, 1A, 13W	22a	Mat	AD162, 2SB474, 2SB481
2SB449	Ge-P	NF/S-L, 50V, 3,5A, 22,5W(Tc=50°)	23a	Mat	AD149, AD188..167, AUY28, 2N1540, ++
2SB450	Ge-P	NF, 25V, 0,5A, 0,2W	2a	Mit	AC128, AC153, AC188, 2SB324, 2SB415
2SB450A	Ge-P	=2SB450: 32V	2a	Mit	AC128, AC153, 2SB324, 2SB415
2SB451	Ge-P	NF-Tr/E, 25V, 1A, 0,3W, B=80	2a	Mit	AC128, AC153, AC188, 2SB324, 2SB415
2SB452	Ge-P	=2SB451: B=150	2a	Mit	AC128, AC153, AC188, 2SB324, 2SB415
2SB452A	Ge-P	=2SB451: 32V	2a		AC128, AC153, 2SB324, 2SB415
2SB453	Ge-P	NF/S, 30V, 0,3A, 0,25W	2a	Mit	AC128, AC153, AC188, ASY46, 2SB475
2SB454	Ge-P	=2SB453: 60V	2a	Mit	ACY39, 2N2042..2043
2SB455	Ge-P	=2SB453: 105V	2a	Mit	ACY39, 2N2042..2043
2SB456	Ge-P	NF/S-L, 80V, 1A, 13W	2a	Fui	—
2SB457	Ge-P	NF, 20V, 0,5A, 0,15W	2a	Mit	AC128, AC153, AC188, 2SB415, 2SB475
2SB457A	Ge-P	=2SB457: 32V	2a		AC128, AC153, 2SB324, 2SB415
2SB458	Ge-P	NF/S-L, 25V, 1A, 4W	22a	Mit	AD162, 2SB474, 2SB481

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2SB458A	Ge-P	=2SB458: 45V	22a		—
2SB458B	Ge-P	=2SB458: 100V	22a		—
2SB459	Ge-P	NF, ra, 30V, 0,05A, 0,12W	2a	Hit	AC125..126, AC151r, ACY32, 2SB173
2SB46	Ge-P	NF, 25V, 0,05A, 0,08W	2a	Tos	AC125..128, AC151, 2SB54, 2SB56
2SB460	Ge-P	=2SB459: 40V	2a	Hit	AC125..126, AC151r, ACY32, 2SB173
2SB461	Ge-P	NF-Tr/E, 35V, 1A, 0,25W	2a	Tos	AC126, AC153, AC188, 2SB324, 2SB415
2SB462	Ge-P	NF/S-L, 60V, 2A, 6W	22a	Tos	—
2SB463	Ge-P	=2SB462: 32V	22a	Tos	AD162, 2SB474, 2SB481
2SB464	Ge-P	NF/S-L, 100V, 6A, 30W	23a	Tos	AL102..103, 2N3616, 2N3618, 2N2527,++
2SB465	Ge-P	=2SB465: 60V	23a	Tos	AL102..103, 2N3612, 2N3614, 2N2527,++
2SB466	Ge-P	NF-L, 40V, 0,5A, 12W	22a	Fui	AD162, 2SB474, 2SB481
2SB467	Ge-P	=2SB488: 60V	22a	Fui	—
2SB468	Ge-P	S-L, TV-HA, 220/90V, 10A, 32W	23a	Hit	AU113, AU213, 2N4324
2SB488A	Ge-P	=2SB468: 270/90V	23a		AU106, AU109, AU111, AU112, 2N5325++
2SB47	Ge-P	NF, ra, 25V, 0,05A, 0,08W	2a	Tos	AC125..126, AC151r, ACY32, 2SB173
2SB470	Ge-P	NF, 25V, 0,05A, 0,06W	2a	Fui	AC125..126, AC151, 2SB54, 2SB56
2SB471	Ge-P	NF-L, 60V, 10A, 30W	23a	Hit	AL100..101, 2N2289, 2N2292, 2N2527,++
2SB472	Ge-P	=2SB471: 60V	23a	Hit	AL100..101, 2N2289, 2N2292, 2N2527,++
2SB473	Ge-P	NF-L, 32V, 1A, 4,3W	22a	Mat	AD162, 2SB474, 2SB481
2SB474	Ge-P	NF-L, 35V, 2A, 12W	22a	Say	(AD162, 2SB481)
2SB475	Ge-P	NF, 20V, 0,3A, 0,15W	2a	Mat	AC128, AC153, AC188, 2SB324, 2SB415
2SB476	Ge-P	NF-Tr/E, 20V, 2A, 6W(Tc=25°)	2a	Mat	AC153, (AC126, AC188)
2SB477	Ge-P	S-L, 30V, 30A, 60W	38a	Mit	2N2152..2158
2SB478	Ge-P	=2SB477: 60V	38a	Mit	2N2153..2155, 2N2157..2159
2SB479	Ge-P	=2SB477: 80V	38a	Mit	2N2155, 2N2158
2SB48	Ge-P	NF, 15V, 0,1A, 0,14W, B=43	2a	Son	AC125..126, AC151, 2SB54, 2SB56
2SB480	Ge-P	=2SB477: 100V	38a	Mit	2N2155, 2N2159
2SB481	Ge-P	NF-L, 32V, 1A, 6W	22a	Mat	AD162, 2SB474
2SB482	Ge-P	NF, 35V, 0,05A, 0,12W	2a	Tos	AC125..126, AC151, 2SB54, 2SB56
2SB483	Ge-P	NF/S-L, 60V, 15A, 60W	23a	Shi	2N1551, 2N1555, 2N1559, 2N1652,++
2SB484	Ge-P	=2SB483: 100V	23a	Shi	2N1552, 2N1558, 2N1560, 2N1652,++
2SB485	Ge-P	=2SB483: 140V	23a	Shi	—
2SB486	Ge-P	=2SB482: ra, 25V	2a	Tos	AC125..126, AC151r, ACY32, 2SB173
2SB487	Ge-P	NF-L, 30V, 0,5A, 5W	≈22	Fui	(AD162, 2SB474, 2SB481)
2SB466	Ge-P	=2SB487: 60V	≈22	Fui	—
2SB489				Tos	—
2SB49	Ge-P	=2SB48: B=83	2a	Son	AC125..126, AC151, 2SB54, 2SB56
2SB490				Tos	—
2SB491	Ge-P	S-L, 250V, 11A, 40W		Say	—
2SB492	Ge-P	NF-Tr/E, 25V, 2A, 6W(Tc=25°)	2a	Say	AC153, (AC126, AC188)
2SB492ST	Ge-P	=2SB492: 50V	2a		—
2SB493	Ge-P	NF/S-L, 40V, 1A, 9W	2a	Mat	(AD162, 2SB474, 2SB481)
2SB494	Ge-P	NF-Tr/E, 25V, 1A, 0,2W, B>36	2a	Mat	AC126, AC153, AC188, 2SB324, 2SB415
2SB495	Ge-P	=2SB494: B>57	2a	Mat	AC126, AC153, AC188, 2SB324, 2SB415
2SB495A	Ge-P	=2SB495: 32V	2a		AC128, AC153, 2SB324, 2SB415
2SB496	Ge-P	NF-Tr/E, 25V, 0,25A, 0,3W	2a	Hit	AC126, AC152..153, AC188, 2SB475
2SB497	Ge-P	Min, NF, ra, 20V, 0,03A, 0,065W	37a	Fui	(AC125..126, AC151r, ACY32, 2SB173)
2SB498	Ge-P	NF, ra, 25V, 0,05A, 0,1W	2a	Nec	AC125..126, AC151r, ACY32, 2SB173
2SB499				Nec	—
2SB50	Ge-P	=2SB48: B=131	2a	Son	AC125..126, AC151, 2SB54, 2SB56
2SB500				Nec	—
2SB501				Nec	—
2SB502	Si-P	NF/S-L, 110V, 3A, 25W, 1MHz	22a	Tos	BD242C, BD244C, BD940, 2SB867,++
2SB502A	Si-P	=2SB502: 5MHz, 1/4µs	22a		BD242C, BD244C, BD940, 2SB867,++
2SB503	Si-P	=2SB502: 70V	22a	Tos	BD242A, BD244A, BD936, 2SB882,++
2SB503A	Si-P	=2SB502: 60V	22a		BD242B, BD244B, BD938, 2SB882,++
2SB504	Si-P	NF/S, 60V, 2A, 1W, 35MHz	2a	Nec	BCX60, BSS17..18, 2N5322..5323
2SB504A	Si-P	=2SB504: 100V	2a		BCX60, BSS17, 2N5322
2SB505	Si-P	=2SB504: 15W	43a	Nec	(BD520, BD528, BD530, BD816,++)
2SB506(A)	Si-P	NF/S-L, 150V, 5A, 60W, 10MHz	23a	Nec	BD246D, 2SB695..696, 2SB713, 2SB816,++
2SB507	Si-P	NF/S-L, 60V, 3A, 30W, 8MHz	17j	Say	BD242A, BD536, BD938, 2SB1064,++
2SB506	Si-P	=2SB507:	17j	Say	BD242A, BD536, BD938, 2SB1064,++
2SB509	Si-P	=2SB507: 4A, 35W	22a	Say	BD244A, BD536, 2N3740..41, 2SA1262,++
2SB51	Ge-P	NF, 30V, 0,2A, 0,2W	2a	Son	AC128, AC152..153, AC188, 2SB324
2SB510	Si-P	NF/S, 60V, 1A, 0,8W, 50MHz	2a	Nec	BC161, BSV16..17, 2N4030..33,++
2SB511	Si-P	NF/S-L, 35V, 1,5A, 10W, 8MHz	17j	Say	BD240, BD242, BD534, 2SA748,++

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2SB512	Si-P	NF/S-L, 60V, 3A, 25W, >3MHz	17j	Mat,Mic	BD242A, BD536, BD936, 2SB1064,++
2SB512A	Si-P	=2SB512: 80V	17j		BD242B, BD536, BD936, 2SA1288,++
2SB513(A)	Si-P	=2SB512(A)	17j	Mat	→2SB512(A)
2SB514	Si-P	NF/S-L, 50V, 2A, 20W, 8MHz	17j	Say,Mic	BD240, BD242, BD536, BD936, ++
2SB515	Si-P	=2SB514:	17j	Say,Mic	→2SB514
2SB518	Ge-P	NF, 20V, 0,1A, 0,15W	2a	Hit	AC125..128, AC151..152, 2SB54, 2SB56
2SB518(-1,-2)	Si-P	S-L, -1=70V, -2=90V, 7A, 60W, >3MHz	23a	Son	BD248B, BDV96, BDX96, 2SA980..982, ++
2SB519(-1,-2)	Si-P	S-L, -1=90V, -2=110V, 10A, 80W, >3MHz	23a	Son	BD246C, BDW22C, 2N6229..31, 2SA1141,++
2SB52	Ge-P	NF, 30V, 0,2A, 0,2W	2a	Son	AC128, AC152..153, AC188, 2SB324
2SB520(-1,-2)	Si-P	S-L, -1=110V, -2=140V, 12A, 100W, >3MHz	23a	Son	BD248F, 2SA908, 2SB555, 2SB681, 2SB817++
2SB521(-1,-2)	Si-P	NF/S-L, -1=60V, -2=85V, 5A, 43W, 7MHz	17j	Son	BD244B, BD544B, BD952, 2SA1012,++
2SB522(-1,-2)	Si-P	=2SB521:	17j		→2SB521
2SB523	Si-P	NF/S-L, 40V, 2A, 10W, 70MHz	17j	Mit,Mic	2SA748, 2SA1288
2SB524	Si-P	=2SB523, 60V, 1,5A	17j		2SA748, 2SA1288
2SB525	Si-P	Uni, 30V, 1A, 0,8W, 100MHz	7b	Mit	BC327..328, BC636, BC636, 2SB809,++
2SB526	Si-P	NF/S-L, 90V, 0,8A, 10W, 70MHz	17j	Mit,Mic	2SA913(A), 2SA985(A), 2SA1111..1112, ++
2SB527	Si-P	=2SB528: 110V	17j	Mit	2SA913(A), 2SA985(A), 2SA1111..1112, ++
2SB528	Si-P	=2SA526: 130V	17j	Mit	2SA913(A), 2SA965A, 2SA1111..1112, ++
2SB529	Si-P	NF/S-L, 40V, 2A, 10W, 70MHz	17j	Mit,Mic	2SA748, 2SA1288
2SB53	Ge-P	NF, 30V, 0,25A, 0,2W	2a	Son	AC128, AC152..153, AC188, 2SB324
2SB530	Si-P	NF/S-L, 110V, 8A, 80W	23a	Tos	BD246C, 2SB688, 2SB776, 2SA981..982, ++
2SB531	Si-P	NF/S-L, 90V, 8A, 50W, 8MHz	23a	Tos	BD248B, BD314, BDV94, BDX94, ++
2SB532	Si-P	NF/S-L, 60V, 5A, 60W, 10MHz	23a	Mat	BD248B, BD314, BDV94, BDX94, ++
2SB533	Ge-P	NF/S, 20V, 2A, 6W(Tc=25°)	2a	Mat	2N1036, 2N2564
2SB534	Ge-P	NF, 20V, 0,5A, 0,2W	2a	Hit	AC128, AC153, AC188, 2SB324, 2SB415
2SB535	Ge-P	NF/S, 35V, 1A, 0,25W, 6W(Tc=25°)	2a	Hit	2N1038, 2N2564, (AC128, AC153)
2SB536	Si-P	NF/S-L, 130V, 1,5A, 20W, 40MHz	17j	Nac	2SA968(A, B), 2SA985A, 2SB628(A), ++
2SB537	Si-P	=2SB536	17j	Nec	→2SB536
2SB536	Ge-P	NF/S-L, 65V, 15A, 75W	23a	Hit	2N1551..52, 2N1555..56, 2N1559..60
2SB539(A)	Si-P	NF/S-L, 130V, 10A, 100W, 8MHz	23a	Nec	BD246D, 2SA1148, 2SB555, 2SB681, ++
2SB539B	Si-P	=2SB539(A): 150V	23a		BD246D, 2SA1386(A), 2SB681, 2SB697, ++
2SB539C	Si-P	=2SB539(A): 160V	23a		BD246D, 2SA1147, 2SB697, 2SB817, ++
2SB54	Ge-P	NF, 30V, 0,15A, 0,15W	2a	Tos	AC125..126, AC151, 2SB56, 2SB175
2SB540	Ge-P	NF/S, 50V, 2A, 8W(Tc=25°)	2a	Tos	2N1039, 2N2565
2SB541	Si-P	NF/S-L, 110V, 8A, 80W, 9MHz	23a	Nec	BD246C, 2SA981..962, 2SA1141, 2SB681, ++
2SB542	Si-P	Uni, 20V, 0,5A, 0,3W, 150MHz	7b	Mit	BC327..328, BC636, 2SA1515, 2SB910,++
2SB544(MP,P1,P2)	Si-P	Uni, lo-sat, 25V, 1A, 0,9W, 160MHz	7c(9mm)	Say	2SA968, 2SA1382, 2SB882, 2SB927,++
2SB545				Nec	—
2SB546(A)	Si-P	TV-VA, 200V, 2A, 20W, 5MHz	17c	Nec	BD240F, 2SA1133, 2SB630, 2SB881
2SB547(A)	Si-P	=2SB548(A)	17j	Nec	→2SB548(A)
2SB548	Si-P	NF-L, 100/80V, 0,8A, 10W, 70MHz	14h	Nec	BD140, BD231, 2SA1184, 2SA1220(A), ++
2SB549	Si-P	=2SB548: 120/100V	14h	Nec	2SA1178, 2SA1184, 2SA1220(A), 2SA1358
2SB55	Ge-P	NF, 60V, 0,15A, 0,15W	2a	Tos	ACY24, ASY48, 2N2042..43
2SB550	Si-P	NF/S-L, 100V, 5A, 25W, 20MHz	22a	Nec	BD244C, BD540C, BD954, 2SB633,++
2SB551	Si-P	NF/S-L, 50V, 3A, 25W, 32MHz	22a	Hit	BD242, BD536, BD936, BDX14, 2SB1064+
2SB552	Si-P	S-L, 220V, 15A, 150W, 3,5MHz	23a	Tos	BUW96, 2SA1117, 2SA1294, 2SB613
2SB553	Si-P	lo-sat, 70V, 7A, 40W, 10MHz	17j	Tos	2SA1290, 2SB921L
2SB554	Si-P	HiFi-NF-E, 160V, 15A, 150W, 6MHz	23a	Tos	2SA908..09, 2SA1118..17, 2SA1147, ++
2SB555	Si-P	=2SB554: 140V, 12A, 100W	23a	Tos	2SA908..909, 2SB681, 2SB697, 2SB817, ++
2SB558	Si-P	=2SB554: 120V, 12A, 100W	23a	Tos	2SA908..909, 2SB681, 2SB697, 2SB817, ++
2SB557(S)	Si-P	=2SB554: 120V, 8A, 90..100W	23a	Tos	BD248D, 2SA981..982, 2SB688, 2SB696, ++
2SB558	Si-P	=2SB554: 100V, 7A, 60W	23a	Tos	BD248C, BDV96, BDX96, 2SA980..962, ++
2SB559	Si-P	NF/S-L, lo-sat, 20V, 1,2A, 8W, 150MHz	14h	Say	BD136, BD227, BD376, 2SB1009,++
2SB56	Ge-P	NF, 30V, 0,15A, 0,15W	2a	Tos	AC128, AC151..153, AC196, 2SB324
2SB560(MP)	Si-P	Uni, lo-sat, 100V, 0,7A, 0,9W, 100MHz	7c(9mm)	Say,Mic	2SA985, 2SB647, 2SA1013, 2SA1275
2SB561	Si-P	Uni, 25V, 0,7A, 0,5W, 350MHz	7c	Hit	(BC327..328, BC636, 2SA1705,++)
2SB562	Si-P	=2SB561: 1A, 0,9W	7c(9mm)	Hit	(2SA966, 2SA1362, 2SB978, 2SB692,++)
2SB563	Si-P	NF/S-L, 60V, 3A, 25W	22a	Nec	BD242B, BD538, BDX14, 2SA1288,++
2SB564	Si-P	Uni, 30V, 1A, 1W, 110MHz	9b	Nec	BC327..328, BC636, 2SB909, 2SB1118,++
2SB565(A)	Si-P	NF/S-L, 70V, 4A, 40W, 15MHz	17j	Hit	BD244B, BD538, BD952, 2SB633,++
2SB566(A)	Si-P	=2SB565	17j	Hit	→2SB565
2SB566(A)K	Si-P	=2SB565: hi-rel Varsion, 300/3000ns			—
2SB567	Si-P	NF/S-L, 200V, 2A, 30W	17j	Hit	BD240F, 2SA1133, 2SB630, 2SB861
2SB568	Si-P	=2SB567	17j	Hit	→2SB567
2SB569	Si-P-Darl	NF/S-L, 40V, 4A, 40W, B=6000	14h	Mot	BD676, BD776, 2N6034..6036,++
2SB56A	Ge-P	=2SB56: 45V	2a		ACY24, ASY48, ASY78..77, 2N1189..90

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2SB57	Ge-P	NF, 30V, 0,1A, 0,1W	2a	Fui	AC125..126, AC151, 2SB54, 2SB56
2SB570	Si-P-Darl	=2SB569: 60V	14h	Mot	BD678, BD778, 2N6035..6036,++
2SB571	Si-P-Darl	=2SB569: 60V	14h	Mot	BD680, BD760, 2N6036
2SB572	Si-P	NF/S-L, 40V, 3A, 30W	14h	Mot	BD176, BD186, BD436, 2N5193..95,++
2SB573	Si-P	=2SB572: 60V	14h	Mot	BD178, BD190, BD440, 2N5194..95,++
2SB574	Si-P	=2SB572: 60V	14h	Mot	BD160, BD442, 2N5195
2SB575	Si-P	NF/S-L, 40V, 4A, 40W	14h	Mot	BD186, BD436, 2N5193..5195
2SB576	Si-P	=2SB575: 60V	14h	Mot	BD190, BD440, 2N5194..5195
2SB577	Si-P	=2SB575: 80V	14h	Mot	BD442, 2N5195
2SB578	Si-P	NF/S-L, 70V, 10A, 90W	16h	Mot	BD206, MJE2955
2SB579	Si-P	NF/S-L, 60V, 5A, 75W	16h	Mot	BD200, 2N5974..5976
2SB57A	Ge-P	NF, 45V, 0,5A, 0,225W	2a	Fui	ASY76..77, 2N1169..90
2SB58	Ge-P	NF, 12V, 0,05A, 0,1W	2a	Fui	AC125..126, AC151, 2SB54, 2SB56
2SB560	Si-P	=2SB579: 80V	16h	Mot	2N5975..5976
2SB581	Si-P	=2SB579: 100V	16h	Mot	2N5976
2SB582	Si-P-Darl	NF/S-L, 60V, 8A, 75W, B=3000	16h	Mot	(BDV64(A..C), TIP145..147)
2SB583	Si-P-Darl	=2SB582: 60V	16h	Mot	(BDV64A..C, TIP146..147)
2SB564	Si-P-Darl	=2SB582: 100V	16h	Mot	(BDV64B..C, TIP147)
2SB585	Si-P-Darl	NF/S-L, 60V, 8A, 100W, B=3000	23a	Mot	BDV64(A..C), BDX84A..C, BDX86A..C,++
2SB586	Si-P-Darl	=2SB565: 60V	23a		BDV64A..C, BDX64B..C, BDX86B..C,++
2SB587	Si-P-Darl	NF/S-L, 60V, 12A, 150W, B=3000	23a	Mot	BDV64(A..C), BDW64A..D, BDX68A..C,++
2SB588	Si-P-Darl	=2SB567: 80V	23a	Mot	BDV64A..C, BDW84B..D, BDX86B..C,++
2SB589	Si-P-Darl	=2SB587: 100V	23a	Mot	BDV64B..C, BDW84C..D, BDX86C,++
2SB59	Ge-P	NF/S, 30V, 0,1A, 0,15W	2a	Fui	AC125..126, AC151, 2SB54, 2SB56
2SB592				Hit	—
2SB593				Hit	—
2SB594				Hit	—
2SB595	Si-P	HiFi-NF-E, 100V, 5A, 40W, 5MHz	17j	Tos	BD244C, BD544C, BD954, 2SB633,++
2SB596	Si-P	HiFi-NF-E, 60V, 4A, 30W, >3MHz	17j	Tos	BD244B, BD536, BD952, 2SB920,++
2SB597				Tos	—
2SB596	Si-P	Uni, lo-sat, 25V, 1A, 0,5W, 180MHz	7c	Say, Mic	2SB692, 2SB926..927, 2SB1229
2SB599	Si-P	S-L, 200V, 2A, 30W	22a	Nec	BD240F, 2SA1133, 2SB630, 2SB861
2SB60(A)	Ge-P	NF, 20V, 0,05A, 0,15W	2a	Fui	AC125..126, AC151, 2SB54, 2SB56
2SB600	Si-P	NF-L, S-L, 200V, 10A, 200W, 14MHz	23a	Nec	MJ15016, 2SA1116..17, 2SB613, 2SB645,++
2SB601	Si-P-Darl+Di	NF/S-L, 100V, 5A, 30W, B>2000	17j	Nec	BD650, BD902, BDW24C, BDW64C..D,++
2SB602				Nec	—
2SB603	Si-P	NF/S, 500V, 0,5A, 0,6W	2a	Nec	2N5096
2SB604	Si-P	NF/S-L, 70V, 4A, 30W, 10MHz	17j	Mat	BD244A, BD538, BD952, 2SB920,++
2SB605	Si-P	Uni, 60V, 0,7A, 1W, 120MHz	9b	Nec	BC638, BC640, 2SB647, 2SB910, 2SB1116+
2SB606	Si-P	S/Vid, 250V, 0,5A, 0,8W, 200/2000ns	2a	Fui	BFT44..45, MJ5415..16, 2N5416
2SB607	Ge-P	NF/S, 30V, 1A, 3W(Tc=25°)	2a	Mat	AC126, AC153, AC188, 2N1036, 2N2564
2SB606(A)	Si-P	NF/S-L, 180V, 2A, 30W	17j	Hit	BD240E, 2SA1133, 2SB628A, 2SB861, 2SB991
2SB609	Si-P	NF/S-L, 100V, 4A, 40W	22a	Hit	BD244C, BD540C, BD954, 2SB550,++
2SB61	Ge-P	NF, 30V, 0,05A, 0,15W	2a	Fui	AC125..126, AC151, 2SB54, 2SB58
2SB610				Hit	—
2SB611(A)	Si-P	NF/S-L, 150V, 7A, 60W	23a	Hit	BD246D, 2SB696, 2SB713, 2SB816,++
2SB612(A)	Si-P	NF/S-L, 160V, 12A, 100W	23a	Hit	MJ15016, BD746F, 2SA1147, 2SB645,++
2SB613	Si-P	S-L, 250V, 15A, 150W	23a	Hit	BUW42, MJ16023, MJ15025
2SB614				Mit	—
2SB615	Si-P-Darl	NF/S-L, 110V, 7A, 80W, B>1100	17c (B)	Mit	BDV64C, BDX62C, BDX64C, 2SA1183
2SB616(A)	Si-P	NF/S-L, 100V, 5A, 80W, 22MHz	19j	Nec	2SA986, 2SB758(A), 2SB773(A)
2SB617(A)	Si-P	=2SB616(A): 120V, 8A, 70W, 14MHz	19j	Nec	2SA986, 2SB758(A), 2SB773A
2SB618(A)	Si-P	=2SB616(A): 150V, 7A, 60W, 14MHz	19j	Nec	—
2SB619	Ge-P	NF/S, 32V, 1,3A, 0,3W	2a	Mat	AC153, 2N1038, 2N2564, (AC126)
2SB62	Ge-P	NF/S-L, 60V, 0,5A, 4W	22a	Tos	—
2SB620	Si-P	Uni, 25V, 0,05A, 0,25W, 100MHz	7c	Mat	BC213, BC258, BC308, BC558,++
2SB621 (NC)	Si-P	Uni, 30V, 1A, 0,75W, 200MHz	7c	Mat, Mic	BC327..326, BC636, BC638, 2SB809,++
2SB621A	Si-P	=2SB621: 60V	7c		BC638, BC640, 2SA1705, 2SB647,++
2SB622	Si-P	S, 400V, 0,3A, 0,6W, 10MHz	2a	Sak	2N5093..96, 2SB603
2SB623				Nec	—
2SB624	Si-P	SMD, NF, 30V, 0,7A, 180MHz	35a	Nec	BCW67..68, 2SA1621
2SB624R	Si-P	=2SB624:	35d		BCW67R..66R
2SB625	Si-P	NF/S-L, 100V, 7A, 60W, 7MHz	23a	Mat	BD246C, BDV96, BDX96, 2SA960..962,++
2SB626	Si-P	=2SB625: 120V, 8A, 60W, 6MHz	23a	Mat	BD246C, 2SA980..982, 2SA1141,++
2SB627	Ge-P	NF/S-L, 40V, 10A, 13W	2a	Mat	AD136, AUY35..36
2SB626	Si-P	NF/S-L, 160V, 1,5A, 20W, 40MHz	17j	Nec	2SA913A, 2SA1112, 2SB608, 2SB861,++

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2SB626A	Si-P	=2SB628 :160V	17j		2SA913A, 2SA1112, 2SB608, 2SB861,++
2SB629				Nec	—
2SB63	Ge-P	=2SB62: 32V	22a	Tos	AD162, 2SB474
2SB630	Si-P	NF/S-L, 200V, 2A, 25W, 4MHz	17j	Nec	BD240F, 2SA1133, 2SB661
2SB631	Si-P	NF/S-L, lo-sat, 100V, 1A, 6W, 110MHz	14h	Say	BD140, BD231, BD380, 2SA1184,++
2SB631K	Si-P	=2SB631: 120V	14h		2SA1178, 2SA1164, 2SA1220(A), 2SA1358
2SB632	Si-P	NF/S-L, 25V, 2A, 10W, 100MHz	14h	Say	BD330, BD376, 2SB1009,++
2SB632K	Si-P	=2SB632: 35V	14h		BD376, 2SB744(A), 2SB1009,++
2SB633	Si-P	NF/S-L, 100V, 6A, 40W, 15MHz	17j	Say	BD244C, BD544C, BD602
2SB633P	Si-P	=2SB633: 50W	19j		2SB617..618, 2SB773(A), 2SB758(A)
2SB634	Si-P	NF/S-L, 120V, 7A, 60W, 15MHz	23a	Say	BD246C, 2SA1141, 2SB981..962,++
2SB635	Ge-P	NF, 32V, 0,15A, 0,15W	7c(9mm)	Mat	AC125..126, AC151, 2SB54, 2SB56
2SB638	Ge-P	NF, ra, 32V, 0,15A, 0,15W	7c(9mm)	Mat	AC125..126, AC151r, ACY32, 2SB173
2SB637(K)	Si-P	Uni, 50V, 0,1A, 0,3W, 200MHz	7c	Hit	BC212, BC257, BC307, BC557,++
2SB638(H)	Si-P-Darl+Di	NF/S-L, 100V, 10A, 60W, B>1000	23a(B)	Hit	BDV64B, BDX64C, BDX66C, 2N6052,++
2SB639(H)	Si-P-Darl+Di	=2SB638: 100W	23a(B)	Hit	BDV84B, BDX64C, BDX86C, 2N6052,++
2SB64	Ge-P	NF/S-L, 100V, 6A, 25W	23a	Tos	AL102..103, 2N3616, 2N3816, 2SB231
2SB640	Ge-P	NF, 25V, 0,3A, 0,15W	7c(9mm)	Mat	AC12S, AC152..153, AC188, 2SB475
2SB641	Si-P	Uni, 30V, 0,1A, 0,4W, 80MHz	9c	Mat	BC213, BC266, BC308, BC558,++
2SB842	Si-P	=2SB641: 60V	9c	Mat	BC212, BC256, BC266, BC556,++
2SB843	Si-P	Uni, 30V, 0,5A, 0,6W, 200MHz	9c	Mat	BC327..328, BC638, BC638, 2SA1515,++
2SB644	Si-P	=2SB643: 60V	9c	Mat	BC638, BC640, 2N5400..01, 2SA965,++
2SB845	Si-P	NF/S-L, 200V, 15A, 150W, 12MHz	23a	Tos	MJ15016, 2SA909, 2SA1116..17, 2SB613
2SB846(A)	Si-P	Uni, 120V, 0,05A, 0,9W, 140MHz	7c(9mm)	Hit	2SA1124, 2SA1281, 2SA1265(A), 2SA1482
2SB847(A)	Si-P	Uni, 120V, 1A, 0,9W, 140MHz	7c(9mm)	Hit	2SA1013, 2SA1275, 2SB1212
2SB646(A)	Si-P	NF/S/Vid-L, 160V, 0,05A, 140MHz	14h	Hit	BF470, BF472, BF416, BF416, 2SA1352
2SB649(A)	Si-P	NF/S/Vid-L, 160V, 1,5A, 140MHz	14h	Hit	2SA1249
2SB65	Ge-P	NF/S, 30V, 0,1A, 0,15W	2a	Ful	AC125..126, AC151, 2SB54, 2SB56
2SB650(H)	Si-P-Darl+Di	NF/S-L, 100V, 15A, 100W, B>1000	23a(B)	Hit	BDV66A, BDW84C, BDX66B, MJ4032,++
2SB652				Hit	—
2SB653(A)	Si-P	NF/S-L, 120V, 7A, 60W, 20MHz	23a	Hit	BD246C, 2SA1141, 2SA981..982,++
2SB654(A)	Si-P	=2SB653(A): 60W	23a	Hit	BD246C, 2SA1141, 2SA981..982,++
2SB655(A)	Si-P	NF/S-L, 160V, 12A, 100W, 20MHz	23a	Hit	2SA1227A, 2SA1386, 2SB554, 2SB697,++
2SB656(A)	Si-P	=2SB656(A): 125W	23a	Hit	MJ15016, 2SA909, 2SA1116..17, 2SB554,++
2SB66(H)	Ge-P	NF, 30V, 0,07A, 0,15W	2a	Hit	AC125..126, AC151, 2SB54, 2SB56
2SB668	Si-P-Darl	NF/S-L, 60V, 3A, 25W, B>1000	17c(B)	Mat	BD716, BDW24A, BDW54A, 2SB751,++
2SB668A	Si-P-Darl	=2SB668: 60V	17c(B)		BD718, BDW24B, BDW54B, 2SB751A,++
2SB689	Si-P-Darl	NF/S-L, 70V, 4A, 40W, B>1000	17c(B)	Mat	BD716, BDW24B, BDW54B, BDW84B,++
2SB669A	Si-P-Darl	=2SB669: 90V	17j		BD902, BDW24C, BDW54C, BDW84C,++
2SB67(H)	Ge-P	NF/S, 30V, 0,15A, 0,35W	1a	Hit	AC125..126, AC151, 2SB54, 2SB56
2SB670	Si-P-Darl	NF/S-L, 90V, 5A, 60W, B>1000	23a	Mat	BDV84B, BDX82B, TIP147, 2SA1163,++
2SB670A	Si-P-Darl	=2SB670: 110V	23a		BDV64C, BDX82C, TIP147, 2SA1163,++
2SB671T	Si-P-Darl	NF/S-L, 100V, 7A, 60W, B>1000	23a	Mat	BDV64B, BDX62B, BDX84C, TIP147,++
2SB671A	Si-P-Darl	=2SB671: 120V	23a		BDV64C, BDW84D, BDX62C, BDX84C
2SB672	Si-P-Darl	NF/S-L, 120V, 6A, 110W, B>1000	23a	Mat	BDV84C, BDV66B, BDW84D, BDX84C
2SB672A	Si-P-Darl	=2SB672: 140V	23a		BDV66C
2SB673	Si-P-Darl+Di	NF/S-L, 100V, 7A, 40W, B>2000	17c(B)	Tos	BD650, BD902, BDW74C, BDX54C,++
2SB674	Si-P-Darl+Di	=2SB673: 80V	17c(B)	Tos	BD648, BD900, BDW74B, BDX54B,++
2SB675	Si-P-Darl+Di	=2SB673: 60V	17c(B)	Tos	BD646, BD698, BDW74A, BDX54A,++
2SB676	Si-P-Darl+Di	NF/S-L, 100V, 4A, 30W, B>2000	17c(B)	Tos	BD902, BDW24C, BDW54C, BDW84C,++
2SB677	Si-P-Darl+Di	=2SB676: 60V	17c(B)	Tos	BD898, BDW24A, BDW54A, BDW84A,++
2SB676	Si-P-Darl	NF/S, 100V, 1,5A, 6W(Tc=25°), B>2000	2a	Tos	(BD682)
2SB679	Si-P-Darl	=2SB676: 10W	17j	Tos	BDW54C, 2SB751B
2SB67A(AH)	Ge-P	=2SB67: 60V	1a		ACY24, ASY46, ASY77, 2SB55
2SB68(H)	Ge-P	NF/S, 105V, 0,1A, 0,05W	2a	Hit	ACY39, 2N2042..2043
2SB661	Si-P	NF/S-L, 150V, 12A, 100W, 13MHz	23a	Tos	BD746E, 2SA906, 2SA1227A, 2SB697,++
2SB682	Si-P	NF/S-L, 100V, 4A, 60W, 8MHz	17j	Mit	BD244C, BD540C, BD954, 2SB633,++
2SB663	Si-P	NF/S-L, 100V, 5A, 40W, 8MHz	17j	Mit	BD244C, BD540C, BD954, 2SB633,++
2SB664				Mit	—
2SB665	Si-P-Darl	NF/S-L, 110V, 7A, 60W, 30MHz, B>200C	77c(F)	Mit	BDV64C, BDW84D, 2SA1163
2SB686	Si-P	HiFi-NF-E, 100V, 6A, 60W, 10MHz	18j	Tos	BD246C, BDV98, 2SA1141, 2SB775..76,++
2SB687				Tos	—
2SB688	Si-P	NF/S-L, 120V, 6A, 60W, 10MHz	18j	Tos	BD246C, 2SA1141, 2SA1146, 2SA1166,++
2SB669	Si-P	NF/S-L, 100V, 4A, 40W	17j	Hit	BD244C, BD540C, BD954, 2SB633,++
2SB69	Ge-P	NF/S-L, 60V, 6A, 25W	23a	Tos	AL102..103, 2N3612, 2N3614, 2SB231,++
2SB690	Si-P	NF/S-L, 100V, 4A, 40W, 20MHz	17j	Hit	BD244C, BD540C, BD954, 2SB633,++

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2SB691	Si-P	NF/S-L, 130V, 5A, 60W, 7MHz	16j	Mat	BD246D, 2SA1146, 2SB695, 2SB713, 2SB816++
2SB692	Si-P	NF/S-L, 150V, 6A, 70W, 7MHz	18j	Mat	BD246D, 2SA1294, 2SA1386A, 2SB695, 2SB713
2SB693(H)	Si-P-Darl+Di	NF/S-L, 100V, 20A, 125W, B>1000	23a(B)	Hit	BDX68B, MJ11013, 2N6287
2SB694(H)	Si-P-Darl+Di	=2SB893: 25A	23a(B)	Hit	BDX68B, MJ11013, MJ11015
2SB695	Si-P	NF/S-L, 170V, 7A, 60W, 7MHz	16j	Mat	BD246E, 2SA1294, 2SA1386A, 2SB713
2SB696(K)	Si-P	NF/S-L, 150V, 6A, 60W, 15MHz	23a	Say	BD246D, 2SA1166, 2SB681, 2SB697,++
2SB697	Si-P	NF/S-L, 160V, 12A, 100W, 15MHz	23a	Say	BD746F, 2SA1147, 2SB554, 2SB645,++
2SB697K	Si-P	=2SB697: 180V	23a		MJ15016, BD746F, 2SA1147, 2SB845,++
2SB698	Si-P	Uni, Io-sat, 25V, 0,7A, 0,6W, 250MHz	7c	Say	2SA1703, 2SB892, 2SB926..927
2SB699	Si-P	NF/S-L, 160/120V, 12A, 100W	20j	Hit	2SA1076, 2SA1095, 2SA1166(A), 2SA1215,++
2SB70	Ge-P	NF, 30V, 0,01, 0,125W, β=30	1a	Mat	AC125..12S, AC151, 2SB54, 2SB56
2SB700(A)	Si-P	=2SB899: 160/140V	20j	Hit	2SA1076, 2SA1095, 2SA11..66(A), 2SA1215,++
2SB701	Si-P	NF/S-L, 180V, 12A, 120W	20j	Hit	2SA1076, 2SA1095, 2SA11..68(A), 2SA1215,++
2SB702(A)	Si-P	NF/S-L, 180V, 12A, 125W	20j	Hit	2SA1076, 2SA1095, 2SA11..66(A), 2SA1215,++
2SB703(A)	Si-P	NF/S-L, 100V, 4A, 40W, 18MHz	17j	Nec	BD244C, BD540C, BD954, 2SB882,++
2SB704				Nec	—
2SB705	Si-P	NF/S-L, 140V, 10A, 120W, 17MHz	20j	Nec	2SA1094 1095, 2SA1167, 2SB755,++
2SB705A	Si-P	=2SB705: 150V	20j		2SA1076, 2SA1095, 2SA1187, 2SB755, ++
2SB705B	Si-P	=2SB705: 180V	20j		2SA1076, 2SA1095, 2SA1166(A), 2SA1215,++
2SB706	Si-P	NF/S-L, 180V, 10A, 200W, 14MHz	4-SILP	Nec	—
2SB706A	Si-P	=2SB706: 220V	4-SILP		—
2SB707	Si-P	NF/S-L, 80V, 7A, 40W	17j	Nec	BD244B, BD544B, BD800, BD610,++
2SB706	Si-P	NF/S-L, 80V, 7A, 40W	17j	Nec	BD244B, BD544B, BD800, BD810,++
2SB709	Si-P	SMD, Uni, 25V, 0,1A, 80MHz	35a	Mat	BC856. 858, BCW29..30, BCW69..70,++
2SB709A	Si-P	=2SB709 45V	35a		BC658..657, BCW69..70, BCW69,++
2SB71	Ge-P	=2SB70: β=50	1a	Mat	AC125..126, AC151, 2SB54, 2SB56
2SB710	Si-P	SMD, Uni, 30V, 0,5A, 200MHz	35a	Mat	BC807..806, BCW67..68, BCX17..18,++
2SB710A	Si-P	=2SB710: 80V	35a		BCW68, 2SA1366
2SB711	Si-P-Darl	NF/S-L, 80V, SA, 50W, B=1000	17c(B)	Sak	BD646, BD900, BDW24B, BDW74B,++
2SB712	Si-P-Darl	=2SB711: 100V	17c	Sak	BD650, BD902, BDW24C, BDW74C,++
2SB713	Si-P	NF/S-L, 200V, 9A, 100W, 7MHz	16j	Mat	BD246F, 2SA1294
2SB714	Ge-P	NF/S, 20V, 2A, 6W(Tc=25°)	2a	Mat	AC153, 2N1038, 2N2584
2SB715	Si-P	Uni, 100V, 0,05A, 0,75W, 150MHz	7c(9mm)	Hit	2SA1124, 2SA1281, 2SA1265(A), 2SA1482
2SB716	Si-P	=2SB715, 120V	7c(9mm)	Hit	2SA1124, 2SA1281, 2SA1285(A), 2SA1482
2SB716A626A	Si-P	=2SB715, 140V	7c(9mm)		2SA1124, 2SA1261, 2SA1285A, 2SA1482
2SB717	Si-P	NF/S/Vid-L, 180V, 0,05A, 140MHz	17j	Hit	2SA1383, (BF416, BF416, BF470, BF472,++)
2SB718	Si-P	=2SB717: 200V	17j	Hit	(BF416, BF418, BF470, BF472,++)
2SB719	Si-P	NF/S-L, 180V, 2A, 25W, 100MHz	17j	Hit	2SA1079, 2SA1133
2SB720	Si-P	=2SB719: 200V	17j	Hit	2SA1133
2SB721	Si-P	Uni, 25V, 0,7A, 0,825W, 350MHz	7e	Hit	(BC327..328, BC638, 2SB909..810,++)
2SB722	Si-P	NF/S-L, 180V, 15A, 150W	23a	Hit	MJ15016, 2N6609, 2SA1116..17, 2SB554,++
2SB723	Si-P	=2SB722: 200V	23a	Hit	MJ15018, 2SA909, 2SA1116..17, 2SB645,++
2SB724	Si-P	NF/S-L, 80V, 3A, 25W	17j	Mat	BD242A, BD538, BD936, 2SB1064,++
2SB725	Si-P	Uni, 80V, 0,1A, 0,45W, 80MHz	7c	Mat	BC212, BC256, BC266, BC558,++
2SB72S	Si-P	Uni, 80V, 0,1A, 0,25W, 150MHz	7c	Mat	BC556, 2SA970, 2SA1138..1137, 2SA1266++
2SB727(K)	Si-P-Darl+Di	NF/S-L, 120V, 6A, 50W, B>1000	17c(B)	Hit	BD652, BDT20, BDW64D, BDW74D,++
2SB73	Ge-P	NF, ra, 10V, 2mA, 0,02W	2a	Hit	AC125..128, AC151r, ACY32, 2SB173
2SB730				Nec	—
2SB731	Si-P	NF/S-L, Io-sat, 80V, 1A, 10W, 75MHz	14h	Nec	BD138, BD229, BD378, 2SB874..675,++
2SB733	Si-P	NF, Io-set, 20V, 2A, 1W, >50MHz	9b	Nec	2SA1704, 2SB892, 2SB928..927, 2SB1433
2SB734	Si-P	Uni, 80V, 1A, 1W, 80MHz	9b	Nec	2SA1315, 2SA1429, 2SB1116, 2SB1229,++
2SB735				Nec	—
2SB738	Si-P	SMD, Uni, 80V, 0,3A, 100MHz	35a	Nec	BCW68, 2SA1366, 2SB1198
2SB738A	Si-P	=2SB738: 80V	35a		BCX42, 2SB1198
2SB736AR	Si-P	=2SB738: 80V	35d		BCX42R
2SB738R	Si-P	=2SB736:	35d		BCW68R
2SB737	Si-P	NF, ra, 50V, 0,3A, 0,25W, 100MHz	7c	Rhm	BC416, BC580, 2SA970, 2SA1138..1137,++
2SB738	Si-P	NF-E, 20/16V, 2A, 0,9W, 150MHz	7c(9mm)	Hit	2SA1382, 2SB892, 2SB927, 2SB1312
2SB739	Si-P	=2SB738: 20/20V	7c(9mm)	Hit	2SA1382, 2SB892, 2SB927, 2SB1312
2SB73N	Ge-P	=2SB73: 16V, 40mA, 0,065W	2a		AC125..12S, AC151r, ACY32, 2SB173
2SB74	Ge-P	NF, 16V, 15mA, 0,08W	2a	Hit	AC125..128, AC151, 2SB54, 2SB56
2SB740	Si-P	NF-E, 70/50V, 1A, 0,9W	7c(9mm)	Hit	2SA1013, 2SA1315, 2SB847, 2SB1212
2SB741	Si-P	=2SB740: 70/70V	7c(9mm)	Hit	2SA1013, 2SA1315, 2SB647, 2SB1212
2SB742	Si-P	NF/S-L, 20V, 2A, 10W	14h	Nec	BD176, BD234, BD330, BD376,++
2SB743	Si-P	NF/S-L, 40V, 3A, 10W, 55MHz	14h	Nec	BD768, MJE250..254, 2SB986
2SB744(A)	Si-P	NF/S-L, 70V, 3A, 10W, 45MHz	14h	Nec	BD768, BD790, MJE250..254

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2SB745	Si-P	Uni, ra, 35V, 0,05A, 0,4W, 150MHz	9c	Mat	BC214, BC259, BC309, BC559, 2SA1137+
2SB745A	Si-P	=2SB745: 55V	9c		BC416, BC560, 2SA970, 2SA1136..1137,++
2SB746	Si-P	Uni, 25V, 0,5A, 0,4W, 260MHz	7c	Hit	BC327..328, BC636, BC638, 2SB909,++
2SB747	Si-P	NF/S-L, 80V, 5A, 55W, 7MHz	17j	Mat	BD244B, BD544B, BD952, 2SB920L,++
2SB748(A)	Si-P	NF/S-L, 120V, 6A, 60W, 20MHz	20j	Hit	2SA1075..1076, 2SA1094, 2SB705(A,B),++
2SB749(A)	Si-P	NF/S-L, 120V, 7A, 80W, 20MHz	20j	Hit	2SA1075..1076, 2SA1094, 2SB705(A,B),++
2SB75(H)	Ge-P	NF, 25V, 0,1A, 0,15W	2a	Hit	AC125..126, AC151, 2SB54, 2SB56
2SB750	Si-P-Darl+Di	NF/S-L, 60V, 2A, 35W, B>1000	17c(B)	Mat	BD716, BDW24A, BDW54A, BDW64A,++
2SB750A	Si-P-Darl+Di	=2SB750: 60V	17c(B)		BD718, BDW24B, BDW54B, BDW64B,++
2SB750B	Si-P-Darl+Di	=2SB750: 100V	17c(B)		BDW24C, BDW54C, BDW64C
2SB751	Si-P-Darl+Di	NF/S-L, 60V, 4A, 40W, B>1000	17c(B)	Mat	BD646, BD898, BDW24A, BDW64A,++
2SB751A	Si-P-Darl+Di	=2SB751: 60V	17c(B)		BD648, BD900, BDW24B, BDW64B,++
2SB751B	Si-P-Darl+Di	=2SB751: 100V	17c(B)		BD650, BD902, BDW24C, BDW64C,++
2SB752				Tos	—
2SB753	Si-P	lo-sat, 100V, 7A, 40W, 10MHz	17j	Tos	2SA1293
2SB754	Si-P	NF/S-L, lo-sat, 50V, 7A, 60W, 10MHz	18j	Tos	2SB827
2SB755	Si-P	NF/S-L, 150V, 12A, 120W, 20MHz	20j	Tos	2SA1076, 2SA1166(A), 2SA1187, 2SA1095,++
2SB756	Si-P	NF/S-L, 200V, 15A, 150W, 20MHz	20j	Tos	2SA1169..1170, 2SA1295, 2SA1333
2SB757	Si-P	NF/S-L, 40V, 15A, 80W	18j	Fjd	BD250, BD546, BD746, 2SA1292
2SB756	Si-P	NF/S-L, 120V, 7A, 80W	19j	Nec	2SA986, 2SB618
2SB756A	Si-P	=2SB756: 130V	19j		2SA986, 2SB618
2SB759	Si-P	Uni, 25V, 0,05A, 0,25W, 200MHz	40c	Mat	BC213, BC258, BC308, BC558,++
2SB759A	Si-P	=2SB759: 45V	40c		BC212, BC257, BC307, BC557,++
2SB75A(AH)	Ge-P	=2SB75: 45V	2a		ACY24, ASY48, 2SB55
2SB76	Ge-P	NF, 12V, 0,07A, 0,15W	2a	Hit	AC125..126, AC151, 2SB54, 2SB56
2SB760	Si-P	NF/S-L, 60V, 1A, 30W	17j	Mat	BD240A, BD242A, 2SA748, 2SA1288,++
2SB760A	Si-P	=2SB760: 60V	17j		BD240B, BD242B, 2SA985(A), 2SA1288,++
2SB760B	Si-P	=2SB760: 100V	17j		BD240C, BD242C, 2SA985(A), 2SA1393,++
2SB761	Si-P	NF/S-L, 60V, 3A, 35W	17j	Mat	BD242A, BD536, BD936, 2SA1262,++
2SB761A	Si-P	=2SB761: 60V	17j		BD242B, BD536, BD936, 2SB682,++
2SB761B	Si-P	=2SB761: 100V	17j		BD242C, BD936, 2SB633, 2SB682,++
2SB762	Si-P	NF/S-L, 60V, 4A, 40W	17j	Mat	BD244A, BD536, BD950, 2SA1262,++
2SB762A	Si-P	=2SB762: 60V	17j		BD244B, BD538, BD952, 2SB920L,++
2SB762B	Si-P	=2SB762: 100V	17j		BD244C, BD540C, BD954, 2SB633,++
2SB763	Si-P	NF/S-L, 60V, 5A, 60W	18j	Mat	BD246A, BDV92, 2SB775, 2SB688,++
2SB763A	Si-P	=2SB763: 60V	18j		BD246B, BDV94, 2SB775, 2SB688,++
2SB763B	Si-P	=2SB763: 100V	18j		BD246C, BDV96, 2SB775, 2SB666,++
2SB764	Si-P	Uni, 60V, 1A, 0,9W, 150MHz	7c(9mm)	Say	2SA1315, 2SB647, 2SB692, 2SB1041,++
2SB765(K)	Si-P-Darl+Di	NF/S-L, 120V, 3A, 30W, B>1000	17c(B)	Hit	BDT20, BDW54D, BDW64D
2SB766	Si-P	SMD, Uni, 30V, 1A, 200MHz	39b	Mat	BC869, BCX69, 2SA1203, 2SA1314
2SB766A	Si-P	=2SB766: 60V	39b		BCX52..53, 2SA1364, 2SB604, 2SB1025,++
2SB767	Si-P	Uni, 60V, 0,5A, 120MHz	39b	Mat	2SA1368, 2SB789(A), 2SB605..806
2SB768	Si-P	Vid-E, 200V, 2A, 20W, 10MHz	30j	Nec	(2SB928(A), 2SB630, 2SB661)
2SB769				Nec	—
2SB77(H,N)	Ge-P	NF, 25V, 0,1A, 0,15W	2a	Hit	AC125..126, AC151, 2SB54, 2SB56
2SB770				Nec	—
2SB771				Nec	—
2SB772	Si-P	NF/S-L, lo-sat, 40V, 3A, 10W, 60MHz	14h	Nec	BD786, MJE250..254, 2SB744(A)
2SB773	Si-P	NF/S-L, 100V, 6A, 70W	19j	Nec	2SA986, 2SB617, 2SB618, 2SB758(A)
2SB773A	Si-P	=2SB773: 120V	19j		2SA986, 2SB617, 2SB618, 2SB758(A)
2SB774	Si-P	hi-Ueb, 30V, 0,1A, 0,4W, 150MHz	7c	Mat	2SB694, 2SB1206, (BC308, BC558)
2SB775	Si-P	NF/S-L, 100V, 6A, 60W, 18MHz	18j	Say	BD246C, BDV96, 2SA1141, 2SB688,++
2SB776	Si-P	NF/S-L, 120V, 7A, 70W, 15MHz	18j	Say	BD246C, 2SA1146, 2SA1186, 2SB688,++
2SB777	Si-P	NF/S-L, 60V, 10A, 80W, <1/3µs	18j	Fjd	BD246B, BDV94, 2SA1141, 2SA1146,++
2SB778	Si-P	=2SB777: 120V	18j	Fjd	BD246C, 2SA1141, 2SA1146, 2SB617,++
2SB779	Si-P	SMD, lo-sat, 25V, 0,5A, 150MHz	35a	Mat	2SA1298, (BC607..806, BCX17..18)
2SB77A(AH, AN)	Ge-P	=2SB77: 45V	2a		ACY24, ASY48, 2SB55
2SB78	Ge-P	NF, 12V, 0,07A, 0,15W	2a	Hit	AC125..126, AC151, 2SB54, 2SB56
2SB780	Si-P	Uni, 30V, 0,5A, 0,4W, 200MHz	40c	Mat	BC327..328, BC636, BC638, 2SB909,++
2SB781	Si-P	NF/S-L, 50V, 4A, 30W	17j	Hit	BD244, BD536, BD950, 2SA1262,++
2SB762	Si-P	=2SB781: 60V	17j	Hit	BD244A, BD536, BD950, 2SA1262,++
2SB763	Si-P	=2SB781: 80V	17j	Hit	BD244B, BD536, BD952, 2SB920L,++
2SB784				Hit	—
2SB785				Hit	—
2SB786	Si-P-Darl	NF/S-L, 40V, 2A, 5W, 150MHz, B=10000	14b(M)	Rhm	2SB794..795, 2SB1008
2SB786A	Si-P-Darl	=2SB786: Iso	14b(M)	Rhm	2SB1310

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2SB787	Si-P	Uni, 120V, 0,05A, 0,625W	7e	Hit	2SA872A, 2SA970, 2SA1285(A), 2SB716(A)++
2SB788	Si-P	Uni, ra, 120V, 0,02A, 0,4W, 150MHz	9c	Mat	2SA872A, 2SA970, 2SA1038, 2SA1136, ++
2SB789	Si-P	SMD, 100V, 0,5A, 120MHz	39b	Mat	BCX53, 2SA1201, 2SA1368, 2SB804..806
2SB789A	Si-P	=2SB789: 120V	39b		2SA1201, 2SB806, 2SB1025
2SB79	Ge-P	NF, 25V, 0,15A, 0,25W	1a	Hit	AC125..126, AC151, 2SB54, 2SB56
2SB790	Si-P	NF, lo-sat, 25V, 0,5A, 0,6W, 150MHz	9c	Mat	2SB892, 2SB926..927, (BC327..328)
2SB791(K)	Si-P-Darl+Di	NF/S-L, 120V, 8A, 40W, B>1000	17c(B)	Hit	BD652, BDT20, BDW74D, BDX54D
2SB792	Si-P	SMD, Uni, ra, 150V, 0,05A, 200MHz	35a	Mat	—
2SB792A	Si-P	=2SB792: 185V	35a		—
2SB793	Si-P	NF-Tr/E, 30V, 1A, 1W, 200MHz	9c	Mat	BC327..328, BC636, BC638, 2SB909, ++
2SB793A	Si-P	=2SB793: 60V	9c		BC327A, BC636, BC638, 2SB1116, ++
2SB794	Si-P-Darl+Di	NF/S-L, 60V, ±1,5A, 10W, B=2k..30k	14b	Nec	BD678, BD778, 2N6035..6036
2SB795	Si-P-Darl+Di	=2SB794: 60V	14b	Nec	BD680, BD780, 2N6036
2SB796	Si-P	NF/S-L, 200V, 10A, 200W, 14MHz	23a	Nec	MJ15016, 2SA909, 2SA1116..17, 2SB723
2SB797				Nec	—
2SB798	Si-P	SMD, Uni, 30V, 1A, 110MHz	39b	Nec	BC869, BCX51, BCX69, 2SA1203, ++
2SB799	Si-P	SMD, Uni, 60V, 0,7A, 120MHz	39b	Nec	BCX53, 2SA1201, 2SB804..806, 2SB1025
2SB80(H)	Ge-P	NF/S-L, 25V, 1A, 4W	22a	Hit	AD162, 2SB474
2SB800	Si-P	SMD, Uni, 60V, 0,3A, 100MHz	39b	Nec	2SA1202, 2SA1368, 2SB767, 2SB789(A)
2SB801	Si-P	SMD, Uni, 45V, 1A, 80MHz	39b	Nec	BCX51..53, 2SA1364, 2SB766A, 2SB1025, ++
2SB802	Si-P	=2SB801: 60V	39b	Nec	BCX52..53, 2SA1364, 2SB766A, 2SB1025, ++
2SB803	Si-P	=2SB801: 100V	39b	Nec	BCX53, 2SB804, 2SB1025
2SB804	Si-P	SMD, Uni, 100V, 1A, 80MHz	39b	Nec	BCX53, 2SB803, 2SB1025
2SB805	Si-P	SMD, Uni, 100V, 0,7A, 75MHz	39b	Nec	BCX53, 2SA1201, 2SB803..804, 2SB1025
2SB806	Si-P	=2SB805: 120V	39b	Nec	2SA1201, 2SB806, 2SB1025
2SB807	Si-P	SMD, NF, ra, 150V, 0,1A, 200MHz	39b	Mat	—
2SB808	Si-P	lo-sat, 20V, 0,7A, 0,25W, 250MHz	40c	Say	2SA1705, 2SB1116, (BC327..328, BC636+)
2SB809				Mit	—
2SB81	Ge-P	NF/S-L, 60V, 0,5A, 2W	22a	Hit	—
2SB810	Si-P	Uni, lo-sat, 30V, 0,7A, 0,35W, 160MHz	40c	Nec	2SA1703, 2SB892, 2SB926..927, 2SB1433
2SB811	Si-P	Uni, 30V, 1A, 0,35W, 110MHz	40c	Nec	BC327..328, BC636, 2SB909, 2SB1118, ++
2SB812	Si-P	NF/S-L, 60V, 4A, 60W	18j	Mat	BD246A, BDV92, 2SA1141, 2SB775..776, ++
2SB812A	Si-P	=2SB812: 80V	18j		BD246B, BDV94, 2SA1141, 2SB775..776, ++
2SB813	Si-P	NF/S-L, 80V, 4A, 40W, 20MHz	17j	Say	BD244A, BD536, BD950, 2SA1262, ++
2SB813K	Si-P	=2SB813: 100V	17j	Say	BD244C, BD954, 2SB833, 2SB682, ++
2SB814	Si-P	SMD, ra, 120V, 0,02A	35a	Mat	2SA1312, 2SB792
2SB815	Si-P	=2SB806: SMD	35a	Say	2SA1298
2SB816	Si-P	NF/S-L, 150V, 8A, 80W, 15MHz	18j	Say	BD248D, 2SA1188, 2SA1227A, 2SB713
2SB817	Si-P	NF/S-L, 160V, 12A, 100W, 15MHz	18j	Say	BD746F, 2SA1294, 2SA1366(A)
2SB818(K)	Si-P-Darl+Di	NF/S-L, 100V, 10A, 60W, B>1000	20j	Hit	2SB853
2SB819	Si-P	NF-Tr/E, 50V, 1,5A, 1W, 150MHz	9c	Mat	MPS750..751, 2SA1315, 2SA1362, 2SB892++
2SB82(H)	Ge-P	=2SB81: 100V	22a	Hit	—
2SB820	Si-P	NF/S-L, 350V, 1A, 15W	30j	Nec	2SA1412, (2SA1009(A), 2SA1238, 2SA1397)
2SB821	Si-P	=2SB737:	9c	Rhm	→2SB737
2SB822	Si-P	NF-Tr/E, 40V, 2A, 0,75W, 100MHz	9c	Rhm	MPS750, 2SA1315, 2SA1382, 2SB911, ++
2SB823	Si-P	NF/S-L, 100V, 6A, 40W	17j	Say	BD244C, BD544C, BD802, 2SB633, ++
2SB824	Si-P	S-L, lo-sat, 80V, 5A, 30W, 30MHz	17j	Say	2SA1012, 2SA1289, 2SB920L
2SB825	Si-P	S-L, lo-sat, 60V, 7A, 40W, 10MHz	17j	Say	2SA1290, 2SB919, 2SB921L
2SB826	Si-P	S-L, lo-sat, 60V, 12A, 40W, 10MHz	17j	Say	2SA1328, 2SB903
2SB827	Si-P	S-L, lo-sat, 60V, 7A, 60W, 10MHz	18j	Say	2SA1292, 2SB922L
2SB828	Si-P	S-L, lo-sat, 60V, 12A, 60W, 10MHz	18j	Say	2SA1292, 2SB922L
2SB829	Si-P	S-L, lo-sat, 60V, 15A, 90W, 20MHz	18j	Say	2SB1230
2SB83(H)	Ge-P	NF/S-L, 40V, 3A, 44W	23a	Hit	AD149, 2N2138, 2N2143, 2SB449, ++
2SB830	Si-P	NF-Tr/E, 20V, 2A, 0,9W	7c(9mm)	Hit	2SA1382, 2SB738..739, 2SB892, 2SB1312, ++
2SB831	Si-P	SMD, Uni, 25V, 0,7A, 85MHz	35a	Hit	BCW67..88, 2SA1298, 2SA1821
2SB832	Si-P	S-L, TV-HA, 1000V, 10mA, 25W, 4,5MHz	17j	Son	—
2SB833	Si-P-Darl+Di	S-L, 60V, 30A, 150W, B=4000	23a	Tos	BDX68A..C, MJ11013, MJ11015, 2SB894
2SB834	Si-P	NF/S-L, 60V, 3A, 30W, 9MHz	17j	Tos	BD242A, BD536, BD636, 2SA1288, ++
2SB835	Si-P	NF-Tr/E, 20V, 1A, 0,1W, 200MHz	9c	Mat	BC327..328, BC636, BC638, 2SB909, ++
2SB836	Si-P	NF/S-L, 25V, 2,5A, 20W	30j	Hit	2SA1243, 2SB906, 2SB982, 2SB1184, ++
2SB836L	Si-P	=2SB836:	14h		BD330, 2SB744(A)
2SB837	Si-P	=2SB836: 35V	30j	Hit	2SA1243, 2SB906, 2SB962, 2SB1184, ++
2SB837L	Si-P	=2SB837:	14h		BD330, 2SB744(A)
2SB838	Si-P	NF/S-L, 50V, 2A, 20W, 130MHz	30j	Hit	2SA1241, 2SB839, 2SB957..958, 2SB1201, ++
2SB838L	Si-P	=2SB836:	14h		BD376, 2SB744(A), 2SB874..875, ++
2SB839	Si-P	=2SB838: 80V	30j	Hit	2SA1593, 2SB957..958, 2SB1215..16, ++

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2SB839L	Si-P	=2SB839:	14h		BD378, 2SB874..875
2SB84(N)	Ge-P	=2SB83: 60V	23a	Hit	AD166..187, 2N2139, 2N2144, ++
2SB840	Si-P	NF/S-L, 180/120V, 1,5A, 20W, 140MHz	30j	Hit	2SA1552, 2SB766
2SB840L	Si-P	=2SB840:	14h		2SA1249, 2SB849
2SB841	Si-P	=2SB840: 180/160V	30j	Hit	2SA1552, 2SB766
2SB841L	Si-P	=2SB841:	14h		2SA1249, 2SB849
2SB842	Si-P	=2SB840: 200V	30j	Hit	2SB768, (2SB928(A), 2SA968B, 2SA1133, ++)
2SB842L	Si-P	=2SB841:	14h		—
2SB843	Si-P	NF/S-L, 50V, 5A, 10W	14h	Hit	2SB1151
2SB844	Si-P	NF/S-L, 120V, 1A, 10W, B=160	30j	Hit	2SA1592, 2SA1225, 2SB959..960, 2SB905, ++
2SB845	Si-P	=2SB944: B=100	30j	Hit	2SA1592, 2SA1225, 2SB959..960, 2SB905, ++
2SB846	Si-P	NF/S-L, 25V, 1A, 10W	30j	Hit	2SA1241, 2SB838, 2SB1182, (2SA748, ++)
2SB847				Nec	—
2SB848	Si-P	NF/S-L, 100V, 6A, 70W	16j	Nec	BD246C, BDV96, 2SA1141, 2SA1166, ++
2SB849	Si-P	NF/S-L, 120V, 7A, 80W, 14MHz	16j	Nec	BD246C, 2SA1141, 2SA1148, 2SA1166, ++
2SB848A	Si-P	=2SB849: 130V	16j		BD246D, 2SA1186, 2SB816, 2SB695, ++
2SB85	Ge-P	NF/S-L, 40V, 10A, 50W	23a	Hit	AL100..101, 2N2288, 2N2291, ++
2SB850	Si-P	NF/S-L, 40V, 10A, 50W	17j	Fjd	BD706, BD806, BD906
2SB850A	Si-P	=2SB850: 60V	17j		BD710, BD810, BD910
2SB851	Si-P	NF-Tr, 80V, 0,7A, 0,75W, 100MHz	9c	Rhm	BC640, 2SA965, 2SB847, 2SB910, ++
2SB852	Si-P-Darl	SMD, 30V, 0,1A, 200MHz, B>1000	35a(M)	Rhm	—
2SB852K	Si-P-Darl	=2SB852: 0,3A	35a(M)		BCV26, BCV46
2SB853	Si-P-Darl	NF/S-L, 100V, 15A, 100W, B>1000	20j	Hit	—
2SB854	Si-P-Darl	=2SB853: 20A, 125W	20j	Hit	—
2SB855	Si-P	NF/S-L, 50V, 2A, 20W, 35MHz	17j	Hit	BD240A, BD242A, 2SA748, 2SA1288, ++
2SB856	Si-P	=2SB855: 3A	17j	Hit	BD242A, 2SA748, 2SA1012, 2SA1288, ++
2SB857	Si-P	NF/S-L, 70/50V, 4A, 40W, 15MHz	17j	Hit	BD244A, BD536, BD950, 2SB890, ++
2SB858	Si-P	=2SB857: 70/60V	17j	Hit	BD244A, BD538, BD952, 2SB890, ++
2SB859	Si-P	NF/S-L, 100V, 4A, 40W, 20MHz	17j	Hit	BD244C, BD540C, BD954, 2SB682, ++
2SB66	Ge-P	=2SB85: 60V	23a	Hit	AL100..101, 2N2289, 2N2292, ++
2SB860	Si-P	NF/S-L, 100V, 4A, 40W	17j	Hit	BD244C, BD540C, BD954, 2SB682, ++
2SB861	Si-P	NF/S-L, 200/150V, 2A, 30W	17j	Hit	BD240F, 2SA1133, 2SB630, 2SB720
2SB862	Si-P-Darl	NF/S-L, 120V, 5A, 30W, 68MHz, B=5000	17j	Fjd	BD852, BDT20, BDW84D, BDX54D
2SB863	Si-P	NF-HiFi-E, 140V, 10A, 100W, 15MHz	18j	Tos	BD248D, 2SA1168, 2SA1227A, 2SB817
2SB864	Si-P	Uni, 55V, 0,1A, 0,3W	7c	Hit	BC212, BC257, BC307, BC557, ++
2SB865	Si-P-Darl	Uni, 60V, 1,5A, 0,9W, B>4000	7c(9mm)	Say	BC678, BSR61..82, 2SB1129, 2SB1406
2SB667	Si-P	NF/S-L, lo-sat, 130V, 3A, 30W, 30MHz	17j	Mat	2SA1844
2SB866	Si-P	=2SB867: 4A, 35W	17j	Mat	2SA1644
2SB669	Si-P	=2SB867: 5A, 40W	17j	Mat	2SA1644
2SB87	Ge-P	=2SB85: 80V	23a	Hit	AL100..101, 2N2289, 2N2292, ++
2SB870	Si-P	=2SB867: 7A, 40W	17j	Mat	—
2SB871	Si-P	NF/S-L, lo-sat, 40V, 10A, 40W, 100MHz	17j	Mat	2SA1291, 2SA1328..29, 2SB903
2SB871A	Si-P	=2SB870: 50V	17j		2SA1291, 2SA1328..29, 2SB903
2SB872	Si-P-Darl+Di	NF/S-L, 60V, 6A, 45W, B>1000	17c(B)	Mat	BD848, BD898, BDW74A, BDX54A, ++
2SB872A	Si-P-Darl+Di	=2SB871: 60V	17c(B)		BD848, BD900, BDW74B, BDX54B, ++
2SB873	Si-P	DC-DC-Conv., E, 30V, 5A, 1W, 120MHz	7c(9mm)	Mat	2SB1288, 2SB1306
2SB874	Si-P	NF/S-L, TV-VA, 100V, 2A, 20W, 250MHz	14h	Hit	BD380, BD792, MJE253..254
2SB875	Si-P	NF/S-L, TV-VA, 100V, 2A, 20W, 250MHz	14h	Hit	BD380, BD792, MJE253..254
2SB876	Si-P	NF/S-L, 120/100V, 1,5A, 20W	14h	Hit	2SA1021, 2SA1249, 2SB849
2SB877	Si-P	=2SB878: 120/110V	14h	Hit	2SA1021, 2SA1249, 2SB849
2SB878	Si-P	NF/S-L, 160V, 1,5A, 10W	17j	Hit	BD240E, 2SA1011, 2SB628A, 2SB861, ++
2SB879	Si-P	NF/S-L, 160V, 1,5A, 10W	17j	Hit	BD240E, 2SA1011, 2SB828A, 2SB861, ++
2SB66	Ge-P	=2SB85: 100V	23a	Hit	AL100..101, 2N2290, 2N2293, ++
2SB880	Si-P-Darl+Di	NF/S-L, 70V, 4A, 30W, B=5000	17c(B)	Say	BD718, BDW24B, BDW54B, 2SB751A, ++
2SB881	Si-P-Darl+Di	=2SB880: 7A, 35W	17c(B)	Say	BD848, BD900, BDW74B, BDX54B, ++
2SB882	Si-P-Darl+Di	=2SB860: 10A, 40W	17c(B)	Say	BDT62A, BDT84A, BDW94B, BDX34B, ++
2SB883	Si-P-Darl+Di	=2SB680: 15A, 70W	16c(B)	Say	BDV88(A..D), BDW84(B..D)
2SBB84	Si-P-Darl+Di	NF/S-L, 110V, 3A, 30W, B=4000	16c(B)	Sey	BDW24C, BDW54D, BDW64D, 2SB751B, ++
2SB885	Si-P-Darl+Di	=2SB884: 5A, 35W	16c(B)	Say	BD852, BD902, BDW24C, BDW84D, ++
2SB886	Si-P-Darl+Di	=2SB884: 8A, 40W	16c(B)	Say	BD852, BD902, BDW74D, BDX54D, ++
2SB887	Si-P-Darl+Di	=2SB884: 10A, 70W	16c(B)	Say	BDV64C, BDW84D, 2SB913
2SB866	Si-P-Darl+Di	Uni, 60V, 0,7A, 0,8W, B=25000	7c	Say	BC878, BC860, BSR61..62, 2SB865
2SB669(F)	Si-P	NF/S-L, 80V, 0,7A, 5W, 100MHz	14b	Rhm	(BD140, BD231, 2SA1220(A), 2SB1007, ++)
2SB89(H)	Ge-P	NF, 25V, 0,15A, 0,25W	1a	Hit	AC128, AC151..153, AC188, 2SB475
2SB890	Si-P	Uni, 50V, 0,5A, 0,4W	7c	Rhm	BC327(A), BC836, BC840, 2SB910, ++
2SB891(F)	Si-P	NF-L, 40V, 2A, 5W, 100MHz	14b	Rhm	2SA1359, 2SB1142..1143

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2SB892	Si-P	NF-Tr/E, Io-sat, 60V, 2A, 1W, 150MHz	7c(9mm)	Say	2SA1315, 2SA1706, 2SB1459
2SB893	Si-P	Uni, Io-sat, 20V, 2,5A, 0,75W, 250MHz	7c	Say	2SB985, 2SB1117, 2SB1300, 2SB1505, ++
2SB894	Si-P	hi-Ueb, 30V, 0,1A, 0,45W, 150MHz	9c	Mat	2SB774, 2SB1206, (BC308, BC558, ++)
2SB895	Si-P-Darl	NF/S-L, 30V, 1A, B=8000	14h	Mat	BD466A .B, BD876, BDX45, 2SB1008, ++
2SB895A	Si-P-Darl	=2SB895: 60V	14h		BD876, BDX45..47, 2SB794..795, ++
2SB896	Si-P	NF/S-L, 40V, 10A, 35W, 150MHz	17j	Mat	2SA1077, 2SA1291
2SB896A	Si-P	=2SB896: 50V	17j		2SA1077, 2SA1291
2SB897	Si-P-Darl+Di	NF/S-L, 100V, ±10A, 60W, B>1000	77c(F)	Nec	BDV64B, BDV66A, BDW84C, TIP147
2SB898	Si-P	NF/S-L, 50V, 3A, 25W	17j	Hit	BD242, BD536, BD936, 2SA1288, ++
2SB899	Si-P	NF/S-L, 50V, 3A, 25W	17j	Hit	BD242, BD536, BD936, 2SA1288, ++
2SB89A(AH)	Ge-P	=2SB89: 45V	1a		ACY24, ASY48, 2SB55
2SB90	Ge-P	NF, 18V, 5mA, 0,04W	37a	Tos	AC125..126, AC151, 2SB54, 2SB56
2SB900	Si-P	NF/S-L, 50V, 4A, 40W	17j	Hit	BD536, BD540A, BD950, 2SA1289, ++
2SB901	Si-P	=2SB900: 60V	17j	Hit	BD536, BD540A, BD950, 2SA1289, ++
2SB902	Si-P	SMD, hi-Ueb, 30V, 0,1A, 150MHz	35a	Mat	2SA1252, (BC858..858, BCW69..70, ++)
2SB903	Si-P	S-L, Io-sat, 60V, 12A, 35W, 120MHz	17j	Say	2SA1328..29, (2SB826)
2SB904	Si-P	NF/S-L, Io-sat, 60V, 20A, 60W, 120MHz	18j	Say	2SB1231
2SB905	Si-P	TV-NF-E, 150V, 1,5A, 10W, 50MHz	30j	Tos	2SA1225, 2SB768, 2SB840..842, ++
2SB906	Si-P	NF/S-L, 50V, 3A, 20W, 9MHz	30j	Tos	2SA1184, 2SA1244, 2SB1202..03
2SB907	Si-P-Darl+Di	NF/S-L, 60V, 3A, 15W, B=5000	30c(B)	Tos	2SB1072, 2SB1214, 2SB1303
2SB908	Si-P-Darl+Di	NF/S-L, 100V, 4A, 15W, B=5000	30c(B)	Tos	2SB1072, (BD902, BDW24C, BDW54C, ++)
2SB909(M)	Si-P	NF-Tr/E, 40V, 1A, 1W, 150MHz	9c	Rhm	BC636, BC638, BC640, 2SB1116(A), ++
2SB91	Ge-P	NF, 18V, 30mA, 0,04W	37a	Tos	AC125..126, AC151, 2SB54, 2SB56
2SB910(M)	Si-P	NF-Tr/E, 60V, 0,7A, 1W, 100MHz	9c	Rhm	BC640, 2SA965, 2SB647, 2SB1116(A), ++
2SB911(M)	Si-P	NF-Tr/E, 40V, 2A, 1W, 100MHz	9c	Rhm	MPS750..751, 2SA1315, 2SA1362, 2SB892++
2SB912	Si-P-Darl+Di	NF/S-L, 70V, 10A, 60W, B=5000	18j	Say	BDV64A, BDV66A, BDW84B, TIP146, ++
2SB913	Si-P-Darl+Di	NF/S-L, 110V, 8A, 60W, B=4000	16c(B)	Say	BDV64C, BDV88B, BDW84D, 2SB897, ++
2SB914	Si-P-Darl+Di	NF/S-L, 70V, 10A, 70W, B=5000	23a(B)	Say	BDV64A, BDW84B, BDX86B, MJ2501, ++
2SB915	Si-P-Darl+Di	NF/S-L, 70V, 15A, 80W, B=5000	23a(B)	Say	BDV66A, BDW84B, BDX66A, MJ4031, ++
2SB916	Si-P-Darl+Di	NF/S-L, 110V, 6A, 70W, B=4000	23a(B)	Say	BDV64C, BDW84D, BDX62C, BDX64C, ++
2SB917	Si-P-Darl+Di	NF/S-L, 110V, 10A, 80W, B=4000	23a(B)	Say	BDV64C, BDW84D, BDX64C, BDX66C, ++
2SB918	Si-P	NF/S/Vid, 250V, 0,5A, 0,5W	7c	Fui	BF492..493, BF423A, BFP26, MPS-A92
2SB919	Si-P	S-L, Io-sat, 60V, 8A, 30W, 120MHz	17j	Say	2SA1290..91, 2SB903
2SB92	Ge-P	NF, 32V, 0,125A, 0,125W	1a	Mat	AC125..126, AC151, 2SB54, 2SB56
2SB920	Si-P	=2SB920L: 120V	17j	Say	2SB869
2SB920L	Si-P	S-L, Io-sat, 90V, 5A, 30W, 20MHz	17j	Say	2SA1293
2SB921	Si-P	=2SB921L: 120V	17j	Say	2SB870
2SB921L	Si-P	S-L, Io-sat, 90V, 7A, 40W, 20MHz	17j	Say	2SB870
2SB922	Si-P	=2SB922L: 120V	18j	Say	2SB1230
2SB922L	Si-P	S-L, Io-sat, 90V, 12A, 80W, 20MHz	18j	Say	2SB1230
2SB923	Si-P	NF/S-L, 120V, 20A, 100W	23a	Say	BD250C, BD746D
2SB924	Si-P	NF/S-L, 120V, 25A, 120W	23a	Say	BD250C
2SB925	Si-P	Io-sat, 40V, 7A, 30W, 150MHz, 100/600ns	17j	Mat	2SA1290..1291, 2SB919
2SB925A	Si-P	=2SB925: 50V	17j		2SA1290..1291, 2SB919
2SB926	Si-P	NF-Tr/E, Io-sat, 30V, 2A, 0,75W	7c	Say	2SB892, 2SB1229, 2SB1433..34
2SB927	Si-P	=2SB926: 2,5A, 1W	7c(9mm)	Say	2SA1362, 2SB892, 2SB985, 2SB1312, ++
2SB928(A)	Si-P	NF/S-L, 200V, 2A, 30W, 30MHz	30j	Mat	(2SA1133, 2SB720, 2SB861, ++)
2SB929	Si-P	NF/S-L, 60V, 3A, 35W, 30MHz	30j	Mat	2SB1266, 2SB1268, 2SB1270, 2SB1449, ++
2SB929A	Si-P	=2SB929: 80V	30j		2SB1270, 2SB1451
2SB93	Ge-P	NF, 30V, 10mA, 0,125W	1a	Mat	AC125..126, AC151, 2SB54, 2SB56
2SB930	Si-P	NF/S-L, 60V, 4A, 40W, 20MHz	30j	Mat	2SB1268, 2SB1270, 2SB1449, 2SB1451
2SB930A	Si-P	=2SB930: 60V	30j		2SB1270, 2SB1451
2SB931	Si-P	NF/S-L, Io-sat, 130V, 3A, 30W, 30MHz	30j	Mat	—
2SB932	Si-P	NF/S-L, Io-sat, 130V, 4A, 35W, 30MHz	30j	Mat	—
2SB933	Si-P	NF/S-L, Io-sat, 130V, 5A, 40W, 30MHz	30j	Mat	—
2SB934	Si-P	NF/S-L, Io-sat, 130V, 7A, 40W, 30MHz	30j	Mat	—
2SB935	Si-P	NF/S-L, Io-sat, 40V, 10A, 35W, 150MHz	30j	Mat	—
2SB935A	Si-P	=2SB935: 50V	30j		—
2SB936	Si-P	NF/S-L, Io-sat, 40V, 10A, 40W, 100MHz	30j	Mat	—
2SB936A	Si-P	=2SB936: 50V	30j		—
2SB937	Si-P-Darl+Di	NF/S-L, 60V, 2A, 35W, 20MHz, B>1000	14b(B)	Mat	(BD716, BDW24A, BDW54A, 2SB751, ++)
2SB937A	Si-P-Darl+Di	=2SB937: 60V	14b(B)		(BD718, BDW24B, BDW54B, 2SB751A, ++)
2SB936	Si-P-Darl+Di	NF/S-L, 60V, 4A, 40W, 15MHz, B>1000	14b(B)	Mat	(BD716, BDW24A, BDW54A, 2SB751, ++)
2SB936A	Si-P-Darl+Di	=2SB936: 60V	14b(B)		(BD718, BDW24B, BDW54B, 2SB751A, ++)
2SB939	Si-P-Darl+Di	NF/S-L, 60V, 8A, 45W, 15MHz, B>1000	14b(B)	Mat	(BD646, BD898, BDW74A, BDX54A, ++)
2SB939A	Si-P-Darl+Di	=2SB939: 60V	14b(B)		(BD650, BD900, BDW74B, BDX54B, ++)

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2SB94	Ge-P	NF, 25V, 0,15A, 0,15W, B>45	2a	Tos	AC 125..126, AC 151, 2SB54, 2SB56
2SB940(A)	Si-P	=2SB928(A): 30W	17c	Mat	2SA1306B, 2SA1668, 2SB1096, 2SB1530
2SB941(A)	Si-P	=2SB929(A):	17c	Mat	BDT 32F, 2SA1635, 2SB1017, 2SB1335
2SB942	Si-P	=2SB930(A):	17c	Mat	BD952F, 2SA1635, 2SB1017, 2SB1335
2SB943	Si-P	=2SB931:	17c	Mat	2SA1850
2SB944	Si-P	=2SB932:	17c	Mat	2SA1650
2SB945	Si-P	=2SB933:	17c	Mat	2SA1650
2SB946	Si-P	=2SB934:	17c	Mat	2SA1651
2SB947	Si-P	=2SB935:	17c	Mat	2SA1327, 2SA1567
2SB947A	Si-P	=2SB935A:	17c		2SA1327, 2SA1567
2SB946	Si-P	=2SB936:	17c	Mat	2SA1327, 2SA1567
2SB946A	Si-P	=2SB936A:	17c		2SA1327, 2SA1567
2SB949	Si-P-Darl+Di	=2SB937:	17c(B)	Mat	BDT 60F, 2SB1223, 2SB1342
2SB949A	Si-P-Darl+Di	=2SB937A:	17c(B)		BDT 60AF, 2SB1024, 2SB1342
2SB95	Ge-P	=2SB94: B=60	2a	Tos	AC 125..126, AC 151, 2SB54, 2SB56
2SB950	Si-P-Darl+Di	=2SB938:	17c(B)	Mat	BDT 60F, 2SB1223, 2SB1342
2SB950A	Si-P-Darl+Di	=2SB936A:	17c(B)		BDT 60AF, 2SB1024, 2SB1342
2SB951	Si-P-Darl+Di	=2SB939:	17c(B)	Mat	BD646F, BDT 62F, 2SB1021, 2SB1224. 25
2SB951A	Si-P-Darl+Di	=2SB939A:	17c(B)		BD946F, BDT 62AF, 2SB1020. 21, 2SB1100
2SB952	Si-P	lo-sat, 40V, 7A, 30W, 150MHz, 100/600ns	30j	Mat	2SB935..36, 2SB1267(2SA1290..91, 2SB919)
2SB952A	Si-P	=2SB952: 50V	30j		2SB935A..36A, 2SB1267, (2SA1290..1291++)
2SB953	Si-P	=2SB952:	17c	Mat	2SA1470. 71, 2SA1643
2SB953A	Si-P	=2SB953: 50V	17c		2SA1470. 71, 2SA1643
2SB954	Si-P	NF/S-L, 60V, 1A, 30W, 500/1500ns	17c	Mat	BD 936F, 2SB1015, 2SB1094, 2SB1375
2SB954A	Si-P	=2SB954: 80V	17c		BD938F, BDT32AF, 2SA1095, 2SA1395
2SB955	Si-P-Darl+Di	NF/S-L, 120V, 10A, 50W, B=4000	17c(B)	Hit	BDT62C, BDT 64C, BDX34D
2SB956	Si-P	SMD, Uni, 20V, 1A, 200MHz	39b	Mat	BC 669, BCX51..53, BCX89, 2SA1364, ++
2SB957	Si-P	NF/S-L, 100V, 2A, 20W, 250MHz	30j	Hit	2SA1593, 2SB768, (2SB928(A))
2SB958	Si-P	NF/S-L, 100V, 2A, 20W, 250MHz	30j	Hit	2SA1593, 2SB768, (2SB926(A))
2SB959	Si-P	NF/S-L, 120V, 1,5A, 20W	30j	Hit	2SA1593, 2SB768, (2SB928(A))
2SB96	Ge-P	NF, 32V, 0,125A, 0,125W	1a	Mat	AC 125..126, AC 151, 2SB54, 2SB56
2SB960	Si-P	NF/S-L, 120V, 1,5A, 20W	30j	Hit	2SA1593, 2SB768, (2SB928(A))
2SB961				Son	—
2SB962(Z)	Si-P	NF/S-L, lo-sat, 40V, 3A, 10W, 60MHz	30j	Nec	2SB1202..03, (2SB906, 2SB1184)
2SB963(Z)	Si-P-Darl+Di	NF/S-L, 60V, ±1A, 8W, B=2k..30k	30j	Nec	2SB907, (BD716, BDW54A, 2SB751, ++)
2SB964	Si-P-Darl+Di	NF/S-L, 60V, 1,5A, 10W, B=8000	30j	Nec	2SB907, (BD716, BDW54A, 2SB751, ++)
2SB965	Si-P	NF/S-L, 120V, 7A, 70W, 75MHz	16j	Nec	BD246C, 2SA1141, 2SA1166, 2SB688, ++
2SB966	Si-P	NF/S-L, 120V, 8A, 80W, 65MHz	16j	Nec	BD246C, 2SA1141, 2SA1186, 2SB668, ++
2SB967	Si-P	NF/S-L, 27V, 5A, 20W, 120MHz	30j	Mat	2SA1242, 2SA1244, 2SA1385, 2SB1203
2SB968	Si-P	NF/S-L, 50V, 1,5A, 20W, 150MHz	30j	Mat	2SB838, 2SB957..960, 2SB1201, 2SB1241
2SB969	Si-P-Darl+Di	NF/S-L, 100V, 15A, 100W, B=5000	16j	Nec	BDV66A, BDW84C, 2SB1079
2SB97	Ge-P	NF, ra, 18V, 5mA, 0,04W	87a	Tos	AC 125..126, AC 151r, ACY32, 2SB173
2SB970	Si-P	SMD, Uni, 15V, 0,5A, 130MHz	85a	Mat	BC 807..808, BCX 17..18, 2SA1326, ++
2SB971	Si-P	NF-Tr/E, 20V, 1A, 1W	7c(9mm)	Mat	2SA966, 2SB738..739, 2SB978, 2SB927
2SB972	Si-P	SMD, Uni, 7V, 0,5A	35a	Mat	BC 807..808, BCX 17..18, 2SA1326, ++
2SB973	Si-P	SMD, Uni, 10V, 0,7A, 260MHz	35a	Hit	BCW67..66, 2SA1298, 2SA1621
2SB974	Si-P-Darl+Di	NF/S-L, 100V, 5A, 30W, B=6000	17c(B)	Nec	BD650, BD902, BDW24C, BDW64C, ++
2SB975	Si-P-Darl+Di	NF/S-L, 100V, 8A, 40W, B=6000	15j	Nec	BD650, BD902, BDW74C, BDX54C, ++
2SB976	Si-P	DC-DC-Conv., 27V, 5A, 0,75W, 120MHz	7c	Mat	2SA1431, 2SB1050, 2SB1266, 2SB1305..07++
2SB977	Si-P-Darl	Uni, 30V, 1A, 0,75W, B>2000	7c	Mat	BC 676, BC 878, BSR60..62, 2SB865, +
2SB977A	Si-P-Darl	=2SB977: 60V	7c		BC 676, BC 878, BSR 60..62, 2SB665, ++
2SB976	Si-P	NF-Tr/E, 40V, 1,5A, 0,9W	7c(9mm)	Hit	2SA1315, 2SA1382, 2SB892, 2SB1312
2SB979	Si-P	NF/S-L, 100V, 5A, 60W, 20MHz	16j	Mat	BD246C, 2SB898, 2SB775..776, 2SB695, ++
2SB98	Ge-P	NF, 30V, 0,05A, 0,125W	2a(B=case)	Nec	AC 125..126, AC 151, 2SB54, 2SB56
2SB960	Si-P	NF/S-L, 120V, 8A, 70W	18j	Mat	BD246C, 2SB688, 2SB776, 2SB695, ++
2SB961	Si-P	NF/S-L, 140V, 7A, 80W	18j	Mat	BD 246D, 2SA1166, 2SB616..817, 2SB695, ++
2SB982	Si-P	NF/S-L, 150V, 9A, 100W	18j	Mat	BD 246D, 2SA1227(A), 2SA1366(A), 2SB817
2SB963	Si-P	NF/S-L, 60V, 7A, 40W, 10MHz, 200/600ns	17j	Shi	BD244A, BD544A, BD798, 2SA1290, ++
2SB984	Si-P	NF-Tr/E, 120V, 1A, 1W, 100MHz	9b	Nec	2SA1013, 2SB647, 2SB1130, 2SB1236, ++
2SB985	Si-P	Tr, lo-sat, 60V, 3A, 1W, 150MHz	7c(9mm)	Say	2SA1086, 2SA1707
2SB986	Si-P	=2SB985: 4A, 10W	14h		—
2SB987	Si-P	NF-Tr/E, 120V, 0,5A, 1W, 250MHz	7c(9mm)	Mat	2SA965, 2SA840, 2SB647, 2SB1297, ++
2SB968	Si-P	NF/S-L, 60V, 3A, 30W, <400/2200ns	17j	Kec	BD242A, BD536, BD936, 2SA1262, ++
2SB969	Si-P	NF/S-L, 80V, 4A, 30W, >3MHz	17j	Kec	BD244A, BD536, BD936, 2SB920L, ++
2SB99	Ge-P	NF, 30V, 0,05A, 0,125W	2a(B=case)	Nec	AC 125..126, AC 151, 2SB54, 2SB56
2SB991	Si-P	NF/S-L, 180V, 1,5A, 20W, 8MHz	17j	Say	BD240E, 2SB608, 2SB628A, 2SB630, 2SB861

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2SB992	Si-P	NF/S-L, lo-sat, 100V, 7A, 40W, 10MHz	15j	Tos	—
2SB993	Si-P	NF/S-L, lo-sat, 70V, 7A, 40W, 10MHz	16j	Tos	2SA1290, 2SB921L
2SB994	Si-P	NF/S-L, 60V, 3A, 30W, 3MHz	15j	Tos	BD242A, BD536, BD936, 2SA1262, ++
2SB995	Si-P	NF/S-L, 100V, 5A, 40W, 5MHz	15j	Tos	BD244C, BD544C, BD954, 2SB633, ++
2SB996	Si-P	NF/S-L, 60V, 3A, 30W, 9MHz	15j	Tos	BD242B, BD536, BD540B, 2SB682, ++
2SB997	Si-P-Darl+Di	NF/S-L, 100V, 7A, 40W, B=6000	15j	Tos	BD650, BD902, BDW74C, BDX54C, ++
2SB996	Si-P-Darl+Di	NF/S-L, 60V, 7A, 40W, B=6000	15j	Tos	BD648, BD900, BDW74B, BDX54B, ++
2SB999	Si-P-Darl+Di	NF/S-L, 60V, 7A, 40W, B=6000	15j	Tos	BD646, BD898, BDW74A, BDX54A, ++
2SC					2SC
2SC100	Si-N	HF/S, 40V, 0,2A, 0,15W, <40/70ns	24b	Nec	BSS11, BSX19..20, 2N2368..69(A), ++
2SC1000(G)	Si-N	Uni, ra, 55V, 0,1A, 0,2W, 80MHz	7c	Tos	BC414, BC550, 2SC2240, 2SC2459, ++
2SC1000GTM	Si-N	=2SC1000: 60V, 0,4W	7c		2SC2240, 2SC2459, 2SC2675, 2SC3378, ++
2SC1001	Si-N	UHF-Tr/E, 40V, 0,5A, PQ>1,2W(470MHz)	2a(E=case)	Tos	BFS50, MRF629, 2N3948, 2SC2852
2SC1002	Si-N	UHF-L, 36V, 1A, PQ=3W(470MHz)	49a	Tos	—
2SC1003	Si-N	UHF-L, 36V, 2A, PQ=6W(470MHz)	49a	Tos	—
2SC1004	Si-N	TV-HA/VA, 1100/700V, 0,5A, 50W	23a	Tos	BU204..206, 2SC1167, 2SD1095
2SC1004A	Si-N	=2SC1004: 1500/800V	23a		BU205..206, 2SD575, 2SD818
2SC1005	Si-N	TV-HA, 1100/600V, 5A, 50W, 3MHz	23a	Tos	BU207..209, 2SC1413, 2SD380(A), ++
2SC1005A	Si-N	=2SC1005: 1400/600V	23a		BU208..209, 2SD360(A), 2SD792, 2SD954++
2SC1006	Si-N	Uni, ra, 50V, 0,03A, 0,3W, 90MHz	2a	Nec	BC184, BC414, BC550, 2SC2240, ++
2SC1007	Si-N	Uni, 60V, 0,2A, 0,3W, 250MHz, 95/240ns	2a	Nec	BC174, BC182, BC190, BC546, 2N3904++
2SC1008	Si-N	Uni, 80V, 0,7A, 0,8W, 75MHz, 120/300ns	2a	Nec, Mic	BC140..141, BC300..301, 2N1889..90, ++
2SC1008A	Si-N	=2SC1008: 100V	2a		BC141, BC300, 2N1889..90, 2N2102, ++
2SC1009JA)	Si-N	SMD, HF-ra, 50V, 0,05A, 250MHz	35a	Nec	BC846..847, BCW71..72, BCW81, ++
2SC1010	Si-N	HF-L, 60V, 2A, 80W, 16MHz	22a	Tos	BD239A, BD241A, BD935, 2SC1398, ++
2SC1010	Si-N	Uni, ra, 50V, 0,03A, 0,3W, 90MHz	2a	Nec	BC164, BC414, BC550, 2SC2240, ++
2SC1011	Si-N	VHF-A/Tr/E, 40V, 0,75A, PQ=3W(150MHz)	51r	Mit	BLW17, 2SC1405
2SC1012(Z)	Si-N	Vid, 165V, 0,06A, 0,75W, >60MHz	2a	Mat, Mic	BF257..259, BF657..859, 2N5058..59
2SC1012A(AZ)	Si-N	=2SC1012: 250V	2a		BF258..259, BF658..859, 2N5058..59
2SC1013	Si-N	NF/S-L, 35V, 1,5A, 7W, 70MHz	13n	Mit	(BD507, BD517, BD525, BD839, ++)
2SC1014	Si-N	=2SC1013: 50V	13n	Mit	(BD509, BD519, BD527, BD641, ++)
2SC1015	Si-N	UHF-L, 40V, 3A, PQ=14W(450MHz)	55r	Mit	BLW15, BLX69
2SC1016	Si-N	UHF-Tr/E, 35V, 0,5A, PQ=1,3W(500MHz)	51r	Mit	BLW12, BLX66
2SC1017	Si-N	AM-E, 75V, 1A, PQ=0,08W(27MHz)	13n	Mit	—
2SC1018	Si-N	AM-E, 75V, 1A, PQ=1,4W(27MHz)	13a	Mit	—
2SC1019	Si-N	UHF-L, 60V, 4A, PQ=28W(500MHz)	60c	Mit	2N6104
2SC101A	Si-N	=2SC100: 70V, 5A, 35W, 20MHz	22a		BD243A, BD539B, BD951, 2SC3253, ++
2SC102	Si-N	HF/S-L, 50V, 7A, 100W, 20MHz	38a	Tos	(BD245, BDV91, 2SC3256, 2SD895..896)
2SC1020	Si-N	UHF-L, 60V, 6A, PQ=45W(500MHz)	60c	Mit	—
2SC1021	Si-N	VHF-L, 60V, 6A, PQ=45W(90MHz)	55r	Mit	(BLX15)
2SC1022	Si-N	VHF-L, 60V, 6A, PQ=45W(150MHz)	55r	Mit	—
2SC1023	Si-N	HF, 25V, 25mA, 200MHz	7c	Fui	BF240..241, BF254..255, BF594..595, ++
2SC1024	Si-N	TV-VA, 60V, 3A, 25W, 8MHz	22a	Say	BD241A, BD935, 2N4232, 2SC3252, ++
2SC1025	Si-N	S-L, TV-HA, 200V, 3A, 25W, 8MHz	22a	Say	BU406..406, 2SC1025, 2SD1136, 2SD1159
2SC1026	Si-N	HF, 25V, 25mA, 200MHz	7c	Fui	BF240..241, BF254..255, BF594..595, ++
2SC1027	Si-N	S-L, 250/60V, 6A, 50W	23a	Say	BU606..608, BUX18(A..C), 2SC2769, ++
2SC1028..1029	Si-N			Say	—
2SC103(A)	Si-N	S, 25(A=30)V, 0,05A, 0,25W, >200MHz	2a	Tos	BC166, BC183, BC238, BC548, 2N2221++
2SC1030	Si-N	NF-L, 150/80V, 6A, 50W, 10MHz	23a	Hit	BD245D, 2N3442, 2SD551, 2SD1048, ++
2SC1031	Si-N	S-L, 300/300V, 2A, 30W, 15MHz, <5/15µs	22a	Fui, Nec	BUX67A..C, 2N3564, 2SC1504, 2SC2023, ++
2SC1032	Si-N	HF, 25V, 25mA, 0,15W, 200MHz	7c	Fui	BF240..241, BF254..255, BF594..595, ++
2SC1033	Si-N	Nix, Vid, 200/150V, 25mA, 0,3W, 150MHz	2a	Mat, Mic	BF298..299, BF420, BF422, BF483, ++
2SC1033A	Si-N	=2SC1033: 250/200V	2a		BF298..299, BF420, BF422, BF483, ++
2SC1034	Si-N	S-L, TV-HA, 1100V, 1A, 25W, 5MHz	22a	Son	BU505, 2SD470, 2SD948, 2SD1492
2SC1035	Si-N	VHF/UHF-V, ra, 30V, 0,02A, 700MHz	5q	Say	BF377..378, BF669, BF763, 2N2857, ++
2SC1036	Si-N	VHF/UHF-M/O, 30V, 0,02A, 700MHz	5q	Say	BF377..378, BF889, BF763, 2N2857, ++
2SC1037	Si-N	VHF-L, 60V, 4A, PQ=33W(160MHz)	49a	Nec	—
2SC1036	Si-N	VHF-Tr/E, 40V, 0,15A, PD=0,8W(2,3GHz)	55s	Nec	BFQ34, BFR94, BFT98, 2SC1041
2SC1039	Si-N	VHF-Tr/E, 40V, 0,25A, PQ=1,4W(2,3GHz)	55s	Nec	BFQ88, BFT98, 2SC1042
2SC104(A)	Si-N	Uni, 25(A=30)V, 0,05A, 0,25W, 250MHz	2a	Tos	BC166, BC183, BC236, BC548, 2N2221++
2SC1040	Si-N	UHF-L, 40V, 1,2A, PQ>8W(500MHz)	55s	Nec	BLW91, MRF321, MRF331
2SC1041	Si-N	UHF-A/Tr/E, 40V, 0,15A, PQ=0,9W(2GHz)	55s	Nec	BFQ34, BFR94, BFT99, 2SC1038
2SC1042	Si-N	UHF-A/Tr/E, 40V, 0,25A, PQ=1,6W(2GHz)	55s	Nec	BFQ68, BFT98, 2SC1039
2SC1043	Si-N	UHF-A/Tr, ra, 45V, 0,3A, 2,2GHz	55s	Nec	BFQ88
2SC1044	Si-N	VHF/UHF, ra, 1000MHz	5q	Nec	BF377..378, BF689, BF763, 2N2857, ++
2SC1045	Si-N	TV-VA, 1000/550V, 1A, 25W	23a	Say	BU204..206, 2SC1101, 2SC1167, 2SD1095++

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2SC1046	Si-N	TV-HA, 1000/400V, 3A, 25W	23a	Say	BU207..209, 2SC1875, 2SD819, 2SD1098, ++
2SC1046N	Si-N	=2SC1046: 1200/400V	23a		BU207..209, 2SC1875, 2SD819, 2SD1098, ++
2SC1047	Si-N	AM/FM, 30V, 20mA, 850MHz	7c	Mat, Mic	BF225, BF310, BF314, BF502, 2SC829++
2SC1048	Si-N	Vid, 200V, 0,05A, 0,6W, t20MHz	2a	Mic, Say	BF258..259, BF658..659, 2N5058..59
2SC1049	Si-N			Say	—
2SC105	Si-N	Uni, 30V, 0,08A, 0,25W, 250MHz	2a	Tos	BC168, BC183, BC238, BC548, 2N2221 ++
2SC1050	Si-N	S-L, TV-VA, 300/300V, 1A, 40W, 5MHz	23a	Say	BU104, BU606..606, 2SD916, 2SD1154
2SC1051	Si-N	NF/S-L, 150/100V, 7A, 60W, 8MHz	23a	Say	BD245D, 2N3442, 2SD551, 2SD1048, ++
2SC1051L	Si-N	=2SC1051: 100/80V	23a		BD245C, BDV95, 2SC3181, 2SD1187, ++
2SC1052	Si-N	S, 75V, 1A, 0,8W, <50/70ns	2a	Fui	BSS14, BSV95, 2N3735, 2N5262
2SC1053	Si-N	S, 75V, 0,7A, 0,8W, <40/60ns	2a	Ful	BSS14, BSV95, 2N3735, 2N5262
2SC1054	Si-N	VHF, ra, 35V, 0,05A, 700MHz	5q	Fui	BF377..378, BF689, BF763, 2N2857, ++
2SC1055(H)	Si-N	S-L, 130/60V, 7A, 25W, 25(H=14)MHz	22a	Hit	BU406..406, MJE15030, 2SD866, ++
2SC1058	Si-N	Vid, 260/260V, 0,1A, 0,75W, 180MHz	2a	Son	BF258..259, BF658..659, 2N5058..59
2SC1057	Si-N	UHF-L, 50V, 1A, PQ=6,5W(700MHz)	55r	Ful	—
2SC1058	Si-N	UHF-L, 50V, 2A, PQ=11,5W(700MHz)	55r	Fui	—
2SC1059	Si-N	NF/Vid-L, 300/300V, 0,15A, 8W(Tc=70°)	22a	Hit	2SC1505..1507, 2SC1755..1757, 2SC1905
2SC106	Si-N	HF/S-L, 60V, 2A, 15W, 100MHz, -/230ns	2a	Tos	(BD137, BD228, BD377, 2SD794(A), ++)
2SC1060	Si-N	NF/S-L, 50V, 3A, 25W, 8MHz	17j	Hit, Mic	BD241, BD535, BD935, 2SC3252, ++
2SC1061(K)	Si-N	NF/S-L, 50V, 3A, 25W, 8MHz	17j		BD241, BD535, BD935, 2SC3252, ++
2SC1062	Si-N	S, Vid, 200/200V, 0,1A, 0,7W, 35MHz	2a	Fui, Nec	BF258..259, BF658..659, 2N5058..59
2SC1063	Si-N	S, 10V, 1A, 0,75W, <60/100ns	2a	Son	BSS28..29, BSX12, 2N3426, 2N3724A, ++
2SC1064	Si-N	S, 60V, 1A, 0,8W	2a	old	BSS13, BSS27, BSV77, 2N3735, ++
2SC1065	Si-N	S, 90V, 1A, 0,8W, 400MHz	2a	old	(BSV95, 2N3735)
2SC1066	Si-N	UHF, 20V, 25mA, 800MHz	2a	Fui	BF377..278, BF689, BF763, 2N2857, ++
2SC1067	Si-N	VHF, 35V, 0,05A, 500MHz	2a	Fui	BF225, BF310, BF314, BF502, 2SC1856+
2SC1066	Si-N	UHF, CATV, 25V, 0,15A, 0,5W, 2000MHz	2a	Fui	BFR38, BFW16, 2SC2852
2SC1069	Si-N	S, 100V, 1A, 0,8W, <60/120ns	2a	Fui	—
2SC107	Si-N	=2SC106: 1,5A	2a	Tos	(BD137, BD228, BD377, 2SD794(A), ++)
2SC1070	Si-N	UHF-V, 30V, 0,02A, 900MHz	25p	Nec	2SC2144, 2SC2353, 2SC2484, 2SC2466, ++
2SC1071	Si-N	S, 30V, 0,2A, 0,3W, <45/42ns	2a	Fui, Hit, Nec	BSS11..12, BSX19..20, 2N2368..69(A), ++
2SC1072(A)	Si-N	S, 60V, 0,7A, 0,8W, <40/60ns	2a	Fui, Hi1, Nec	BSS13, BSS27, BSV77, 2N5189, ++
2SC1073(Z)	Si-N	UHF-Tr/E, 36V, 0,5A, PQ=1,8W(500MHz)	55r	Mat	BLW42, BLW79, BLX67, BLY38, 2N5945
2SC1074(Z)	Si-N	UHF-Tr/E, 38V, 1A, PQ=4W(500MHz)	55r	Mat	BLW43, BLW60
2SC1075(Z)	Si-N	UHF-L, 36V, 2A, PQ=8W(500MHz)	55r	Mat	BLW14, BLW44, 2N5946
2SC1076(Z)	Si-N	UHF-L, 38V, 3A, PQ=15W(500MHz)	55r	Mal	BLW15, BLX69
2SC1077(A)	Si-N	VHF-L, 65V, 5..6A, PQ=42W(175MHz)	55r	Tos	BLW25, BLY94, 2N5643
2SC1079	Si-N	S-L, 700/500V, 0,5A, 20W, 2MHz	22a	Tos	MJ4381, 2SC1810, 2SC1828, 2SC3352
2SC1079	Si-N	NF/S-L, 150/150V, 12A, 100W, 4MHz	23a	Tos	BDW12, 2SC1584, 2SD551, 2SD733, ++
2SC108	Si-N	HF/S, 90V, 0,6A, 0,6W, >100MHz	2a	Tos	BC300..301, BC141, BSW39, 2N1990, ++
2SC1080	Si-N	=2SC1079: 110/100V	23a	Tos	BD545D, BDW10, 2SD551, 2SD1105, ++
2SC1081	Si-N	UHF-L, 40V, 2,5A, PQ=14W(500MHz)	55s	Nec	BLW15, BLX69
2SC1082	Si-N	UHF-Tr/E, 50V, 0,5A, PQ=3W(700MHz)	55r	Fui	2N4430
2SC1083(F)	Si-N	UHF-A/Tr/E, 40V, 0,5A, 1600MHz	2a	Fui	BFS50, MRF829, 2N3948
2SC1084	Si-N	Uni, 35V, 0,05A, 0,25W, 300MHz	2a	Fui	BC166, BC183, BC238, BC548, 2SC1890+
2SC1085	Si-N	Uni, 30V, 0,1A, 0,2W, 230MHz	2a	Hit	BC166, BC183, BC238, BC548, 2SD787++
2SC1066	Si-N	TV-HA, 1000V, 4A, 125W, 5MHz	23a	Son	BU207..209, 2SC1348-1..-3, 2SC1413, ++
2SC1087	Si-N	UHF-L, 45V, 3A, PQ=16W(700MHz)	55r	Fui	—
2SC1066	Si-N	NF-E/Vid, 300/200V, 0,1A, 12,5W, >30MHz	17j	Mit	2SC150..1507, 2SC1755..1757, 2SC1819, ++
2SC1069	Si-N	=2SC1088: 300/300V	17j	Mit	2SC1505..1507, 2SC1755..1757, 2SC1819, ++
2SC108A	Si-N	=2SC106: 0,8A, 0,8W	2a		BC300..301, BC141, BSW39, 2N1990, ++
2SC109	Si-N	HF/S, 50V, 0,6A, 0,6W, >70MHz	2a	Tos	BC140..141, BC300..302, BSW39, ++
2SC1090	Si-N	UHF-A, 20V, 0,05A, 0,3W, 3GHz	51s	Nec	BFQ72
2SC1091	Si-N			Nec	—
2SC1092	Si-N	Uni, 150/120V, 0,7A, 0,8W	2a	Nec	BSS43, BSW66, 2SC1860
2SC1093..1094	Si-N			Nec	—
2SC1095	Si-N	NF/S-L, 30V, 2A, 10W, 60MHz	13j	Nec	2SC1226, 2SC1848, (BD505, BD507, ++)
2SC1096(L,Z)	Si-N	NF/S-L, 40V, 3A, 10W, 60MHz	13j	Nec	2SC1226, (BD429, BD613, BD813, ++)
2SC1097	Si-N	NF/S-L, 60V, 1A, 10W, 60MHz	13j	Nec	2SC1848, (BD385, BD415, BD827, ++)
2SC1098(A)(L,Z)	Si-N	NF/S-L, 70V, 3A, 10W, 60MHz	13j	Nec	(BD619)
2SC1099	Si-N	TV-HA, 1200/400V, 3A, 50W	23a	Nec	BU207..209, 2SC1413, 2SD1098, 2SD1102++
2SC109A	Si-N	=2SC109: 70V	2a		BC140..141, BC300..302, BSW39, ++
2SC11	Ge-N	S, 18V, 24mA, 0,055W, 60/140ns	2a	Tos	ASY28..29
2SC110	Si-N	Uni, 40V, 0,2A, 0,75W, 160MHz	2a	Hit	BC140..141, BSV89, 2N3723..3725, ++
2SC1100	Si-N	=2SC1099: 1100/400V	23a	Nec	BU207..209, 2SC1413, 2SD1098, 2SD1102++
2SC1101	Si-N	TV-VA, 1100/500V, 1A, 50W	23a	Nec	BU204..206, 2SC1132, 2SC1187, 2SD1095++

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2SC1102	Si-N	CTV-Vid-E, 300/300V, 0,05A, 11W, >60MHz	22a	Nec	2SC1505..1507, 2SC1755..1757, 2SC1819,++
2SC1103(A)	Si-N	Vid, 250/250V, 0,1A, 0,8W, 80MHz	2a	Nec	BF258..259, BF658..658, 2N5058..58
2SC1104	Si-N	CTV-NF-E, S, 300/300V, 0,7A, 20W	22a	Nec	TIP47..50, 2N3739, 2SC782, 2SC1929, ++
2SC1105	Si-N	CTV-HA-Tr, 300V, 0,1A, 15W, 20MHz	22a	Nec	2SC1505..1507, 2SC1755..1757, 2SC1819,++
2SC1106	Si-N	S-L, CTV-SN, 350/250V, 2A, 80W	23a	Nec	BU126, 2SC1295
2SC1107	Si-N	NF/S-L, 80V, 4A, 25W, 10MHz	17j	Sak	BD243B, BD537, BD951, 2SC3179,++
2SC1106	Si-N	=2SC1107: 100V	17j	Sak	BD243C, BD539C, BD953, 2SD613, ++
2SC1109	Si-N	=2SC1107	17j	Sak	→2SC1107
2SC111	Si-N	Uni, 50V, 0,2A, 0,75W, 160MHz	2a	Hit	BC140..141, BSV77, 2N3723..3725,++
2SC1110	Si-N	=2SC1106	17j	Sak	→2SC1106
2SC1111	Si-N	NF/S-L, 140/80V, 6A, 50W, 10MHz	23a	Sak	BD245D, 2N3442, 2SD551, 2SD1046, ++
2SC1112	Si-N	=2SC1111: 160/100V	23a	Sak	BD245D, 2N3442, 2SD551, 2SD1046, ++
2SC1113	Si-N	NF/S-L, 120/100V, 6A, 40W, 10MHz	22a	Sak	BD243C, BD543D, MJE15028, 2SD666
2SC1114	Si-N	S-L, 300/325V, 4A, 100W, 10MHz	23a	Sak	BU606..608, BUW71, BUX16A..C, ++
2SC1115	Si-N	S-L, 140/80V, 10A, 100W, 10MHz	23a	Sak	BD245D, 2N3442, 2SD551, 2SD1047, ++
2SC1116	Si-N	=2SC1115: 180/120V	23a	Sak	BD245E, BDW14, BDY54, 2SC3263, ++
2SC1116A	Si-N	=2SC1115: 200/140V	23a		MJ15015, BD245F, 2SC1585, 2SC2606, ++
2SC1117(H)	Si-N	UHF, 20V, 0,02A, 850MHz	5q	Hit	BF377..378, BF689, BF763, 2N2857, ++
2SC1118	Si-N	UHF-L, 45V, 2A, PQ=14,5W(500MHz)	55s	Nec	BLW94, BLX94, MRF323
2SC1119	Si-N	UHF, ra, 20V, 0,03A, 0,25W, 4,5GHz	51s	Nec	BFQ71, BFQ85, BFR14, BFR91
2SC112	Si-N	Uni, 40V, 0,2A, 0,75W, 180MHz, <-/127ns	2a	Hit	BC140..141, BSV69, 2N3723..3725,++
2SC1120	Si-N	UHF-L, 35V, 1,5A, PQ=4W(470MHz)	55r	Tos	BLW13..14, BLW43, BLX68, BLY53
2SC1121	Si-N	UHF-L, 35V, 3A, PQ=8,5W(470MHz)	55r	Tos	BLW15, BLW81, BLX69
2SC1122(A)	Si-N	UHF-L, 35V, 4,5A, PQ=14W(470MHz)	55r	Tos	BLW15, BLX69
2SC1123	Si-N	FM/VHF, 35V, 0,1A, 550MHz	7a	Son	BF225, BF310, BF314, BF502, 2SC1393+
2SC1124	Si-N	NF/HF/S-L, 140/140V, 1A, 7,9W, 120MHz	13m	Son	2SC2384, (2SC1913, 2SC2481, 2SC2463,++)
2SC1125	Si-N			Son	—
2SC1126	Si-N	FM/VHF, 550MHz	7f	Son	BF225, BF310, BF314, BF502, 2SC1393+
2SC1127-1,-2	Si-N	NF/Vid-E, 180..210V, 0,1A, 7,9W	13m	Son	BF460..462, MPS-U10, 2SC2224(A),++
2SC1128	Si-N	FM/VHF, 35V, 0,1A, 550MHz	7f	Son	BF370, BF921S, BF959
2SC1129	Si-N	FM/VHF, 35V, 0,03A, 400MHz	7f	Son	BF370, BF921S, BF959
2SC113	Si-N	Uni, 50V, 0,2A, 0,75W, 180MHz, <-/127ns	2a	Hit	BC140..141, BSV77, 2N3723..3725,++
2SC1130	Si-N	S-L, 800/400V, 3,5A, 80W, 4MHz, <1/2µs	23a	Org	BU328(A), BU426(A), BUS11, BUX48, ++
2SC1131	Si-N	=2SC1130: 800/300V	23a	Org	BU326(A), BU426(A), BUS11, BUX46, ++
2SC1132	Si-N	S-L, TV-HA, 1200/500V, 2,5A, 30W	23a	Org	BU204..206, 2SC1875, 2SD1097..1098,++
2SC1133	Si-N	S-L, TV-HA, 1200/500V, 5A, 80W, 4MHz	23a	Org	BU207..209, 2SC1413, 2SD1103..1104,++
2SC1134..1135	Si-N			Org	—
2SC1136	Si-N	S-L, 200/150V, 30A, 200W, 9MHz	68a	Org	2SC2126, 2SC2940, 2SC3224, 2SD540..541++
2SC1137	Si-N			Org	—
2SC1136	Si-N	S-L, 800/400V, 30A, 200W, 9MHz	68a	Org	2SC2204, 2SC2977, 2SD295
2SC1139	Si-N	=2SC1136: 800/300V	68a	Org	2SC2204, 2SC2442, 2SC2977, 2SD644
2SC114	Si-N	Uni, 50V, 0,2A, 0,75W, 60MHz, <-/135ns	2a	Hit	SC140..141, BSV77, 2N3723..3725,++
2SC1140	Si-N	S-L, 800/400V, 15A, 150W, 10MHz	23a	Org	BUS13(A), BUW45..46, BUX46(A..C)
2SC1141	Si-N	=2SC1140: 800/300V	23a	Org	BUS13(A), BUW45..48, BUX48(A..C)
2SC1142	Si-N	S-L, 800/400V, 10A, 125W, 4MHz	23a	Org	BUS12(A), BUW26, BUW35..36, BUX80,++
2SC1143	Si-N	=2SC1142: 600/300V	23a	Org	BUS12(A), BUW25..26, BUW35, BUX80,++
2SC1144	Si-N	S-L, 400/250V, 30A, 200W, 9MHz	68a	Org	2SC1302, 2SC1401, 2SD542..543,++
2SC1145	Si-N	S-L, 700/400V, 20A, 175W, 9MHz	68a	Org	2SC2204, 2SC2977, 2SD295
2SC1146..1149	Si-N			Org	—
2SC115	Si-N	Uni, 30V, 0,05A, 0,75W, 200MHz	2a	Son	BC168, BC183, SC238, BC548, 2N2218++
2SC1150	Si-N	S, 80V, 1A, 0,8W, <35/55ns	2a	Fui	BSS13, BSS27, BSV77, 2N5189, ++
2SC1151	Si-N	S-L, TV-VA, 900/450V, 1A, 50W, 5MHz	23a	Mit	BU204..206, 2SC1101, 2SC1167, 2SD1095++
2SC1151A	Si-N	=2SC1150: 1000/580V	23a		BU204..206, 2SC1101, 2SC1187, 2SD1095++
2SC1152	Si-N	S-L, TV-VA, 300/300V, 2,5A, 50W, 5MHz	23a	Mit	(BU126)
2SC1153	Si-N	TV-HA, 1200/500V, 2,5A, 50W	23a	Mit	BU204..206, 2SC1132, 2SD1097..1098,++
2SC1153A	Si-N	=2SC1153: 1400/500V	23a		BU205..206, 2SC1922, 2SD575, 2SD618, ++
2SC1154	Si-N	=2SC1153: 3,5A	23a	Mit	BU207..209, 2SC1875, 2SD517, 2SD619, ++
2SC1155	Si-N	NF/HF/S-L, 70V, 0,8A, 7W, 70MHz	13n	Mit	(BD417, BD519, BD527, BD529,++)
2SC1156	Si-N	=2SC1155: 90V	13n	Mit	(BD419, BD529, BD829, BD843,++)
2SC1157	Si-N	=2SC1155: 110V	13n	Mit	(BD419, BD529, BD829, BD843,++)
2SC1158	Si-N	UHF-O, 35V, 0,02A, >850MHz	24b	Nec	BF362..363
2SC1159	Si-N	=2SC1158: >600MHz	24b	Nec	BF362..363
2SC116(H)	Si-N	Uni, 50V, 0,2A, 0,75W, 120MHz	2a	Hit	BC140..141, BC300..302, 2N3053,++
2SC1160	Si-N	TV-VA, 200/100V, 1A, 15W, 20MHz	22a	Nec	BD239F, 2SC783, 2SC2238B, 2SD1136, ++
2SC1161(A)	Si-N	=2SC1160: 200/120(A=200/140)V	22a	Nec	BD239F, 2SC783, 2SC2238B, 2SD1136, ++
2SC1162(WT)	Si-N	NF/S-L, 35V, 2,5A, 10W, 160MHz	14h	Hit	BD375, 2SC2677, 2SD1360, 2SD1818, ++

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2SC1163	Si-N	NF/Vid-L, 300V, 0,1A, 20, 8W, 55MHz	14h	Mat	BF459, MJE340, MJE3440, 2SC2376
2SC1164	Si-N	UHF-A, 50V, 0,3A, 0,6W, 1400MHz	5q	Tos	BFR36, 2SC2852
2SC1165	Si-N	UHF-Tr/E, 40V, 0,5A, PQ=1W(470MHz)	2a	Tos	BFS50, MRF629, 2N3948
2SC1166	Si-N	Uni, 60V, 0,2A, 0,6W, 120MHz	9b	Tos	BC174, BC182, BC190, BC546, 2SD767++
2SC1167	Si-N	TV-HA, 1200V, 1,5A, 50W, 3MHz	23a	Tos	BU204..206, 2SC1132, 2SD1095, 2SD1097++
2SC1168	Si-N	Vid-L, 300/300V, 0,15A, 12,5W, 100MHz	22a	Tos	2SC1505..1507, 2SC1755..1757, 2SC1905
2SC1169	Si-N	VHF-Tr/E, 40V, 1A, PQ>2,5W(175MHz)	43a	Tos	(2SC2989)
2SC116T	Si-N	=2SC116: 75V	2a		BC140..141, BC300..301, 2N1613,++
2SC117(H,T)	Si-N	HF/S-L, 75V, 0,6A, 13W, 112MHz	2a	Hit	(BD139, BD230, 2SD1200, 2SD1378,++)
2SC1170	Si-N	TV-HA, 1200/500V, 3,5A, 50W, 4MHz	23a	Tos	BU207..209, 2SC1413, 2SC1875, 2SD1098++
2SC1170A	Si-N	=2SC1170: 1400/500V	23a		BU208..209, 2SC1875, 2SD849..850,++
2SC1170B	Si-N	=2SC1170: 1500/500V	23a		BU208..209, 2SD783, 2SD849..850,++
2SC1171	Si-N	TV-VA, 1100V/800V, 1A, 50W, 2MHz	23a	Tos	BU204..208, 2SC1101, 2SC1167, 2SD1095
2SC1172	Si-N	TV-HA, 1500/600V, 5A, 50W, 3MHz	23a	Tos	BU206(A), 2SC2928, 2SD792, 2SD820,++
2SC1172A	Si-N	=2SC1172: 6A	23a		BU508(A), 2SC3025..28, 2SD649, 2SD821
2SC1172B	Si-N	=2SC1172: 7A	23a		BU508(A), 2SC3027..28, 2SD822, 2SD1018
2SC1173	Si-N	NF/S-L, 30V, 3A, 10W, 100MHz	17j	Mic, Tos	2SC2562, 2SC3252..3253, 2SD1505
2SC1174	Si-N	TV-HA, 1200/500V, 3,5A, 50W, 4MHz	23a	Hit	BU207..209, 2SC1413, 2SC1875, 2SD1098++
2SC1175(NP)	Si-N	Uni, 50V, 0,2A, 0,3(NP=0,4)W, 170MHz	7c	Say, Mic	BC167, BC182, BC237, BC547, 2SC3377+
2SC1176	Si-N	VHF-L, 40V, 1A, PQ=7,5W(175MHz)	55r	Mit	BLW18, BLW37, BLY82, BLY87
2SC1177	Si-N	VHF-L, 40V, 2,5A, PQ=16W(175MHz)	55r	Mit	BLW29, BLY84, BLY88, MRF226, 2N6081
2SC1178(A)	Si-N	VHF-L, 40V, 5A, PQ=23W(175MHz)	55r	Mit	BLW20, BLW31
2SC1179	Si-N			Say	—
2SC118(H)	Si-N	HF/S-L, 80V, 0,6A, 13W, 120MHz	2a	Hit	(BD139, BD230, 2SD1200, 2SD1378,++)
2SC1180	Si-N	UHF, 30V, 0,02A, 800MHz	5q	Say	BF377..378, BF689, BF763, 2N2857,++
2SC1181	Si-N	HF/ZF, 40V, 0,05A, 0,3W, 400MHz		Say	BF198..199, BF224..225, 2SC1855..56,++
2SC1182	Si-N	=2SC1181: 25V		Say	BF198..199, BF224..225, 2SC1855..56,++
2SC1183	Si-N			Son	—
2SC1184	Si-N	TV-VA, 900/500V, 1A, 50W	23a	Nec	BU204..206, 2SC1101, 2SC1167, 2SD1095++
2SC1185	Si-N	S-L, 300/250V, 0,7A, 50W	23a	Nec	2SC1108, 2SC2809
2SC1186	Si-N			Nec	—
2SC1187	Si-N	TV-ZF, 40V, 25mA, 700MHz	7f	Nec	BF198, BF225, BF310, 2SC1855..56,++
2SC1188	Si-N	TV-ZF, 40V, 0,03A, 850MHz	7f	Nec	BF199, BF224, BF311, 2SC1855..58,++
2SC1189	Si-N	TV-ZF, 50V, 25mA, 850MHz	7f	Nec	BF199, BF224, BF311, 2SC1855..56,++
2SC119(H)	Si-N	HF/S-L, 75V, 0,6A, 13W, 130MHz	2a	Hit	(BD139, BD230, 2SD1200, 2SD1378,++)
2SC1190(Z)	Si-N	VHF-L, 36V, 2,5A, PQ=16W(175MHz)	55r	Mat	BLW29, BLY84, BLY88, MRF226, 2N6081
2SC1191(Z)	Si-N	VHF-L, 36V, 3,5A, PQ=27W(175MHz)	60c	Mat	—
2SC1192(Z)	Si-N	VHF-L, 36V, 5A, PQ=37W(175MHz)	60c	Mat	—
2SC1193	Si-N	UHF, ra, 20V, 0,03A, 0,2W, 4,5GHz	24d	Tos	BFQ71, BFQ85, BFR14, BFR91
2SC1194	Si-N			Tos	—
2SC1195	Si-N	S-L, 200V, 2,5A, 100W	23a	Tos	TIP51..54, 2SD632
2SC1196	Si-N	UHF-L, 60V, 0,75A, PQ>3W(700MHz)	55r	Tos	2N4430, 2SC1082
2SC1196A	Si-N	=2SC1196: 45V, 1A, PQ>4W(700MHz)	55r		—
2SC1197	Si-N	UHF-L, 60V, 2A, PQ>9W(700MHz)	55r	Tos	—
2SC1197A	Si-N	=2SC1197: 45V, PQ>12W(700MHz)	55r		—
2SC1198	Si-N	UHF-L, 45V, 3,5A, PQ>18W(700MHz)	55r	Tos	—
2SC1199	Si-N	UHF-A/Tr, ra, 50V, 0,3A, 0,6W, 1400MHz	5q	Tos	BFS50, MRF515, 2SC2852
2SC12	Si-N	NF/S, 60V, 0,25A, 0,18W, 13MHz	2a	Tos	BC140..141, BC300..302, 2N3053,++
2SC120	Si-N	Uni, 40V, 25mA, 0,25W, 200MHz, B>20	2a	Nec	BC167, BC182, BC237, BC547, 2N2218++
2SC1200	Si-N	UHF-Tr/E, 40V, 0,18A, PQ=1,06W(2GHz)		Tos	—
2SC1201..1203	Si-N			Tos	—
2SC1204	Si-N	Uni, 30V, 0,1A, 0,31W, 230MHz	9a	Hit	BC168, BC183, BC236, BC548,++
2SC1205	Si-N	AM/FM, 230MHz	9a	Hit	BF240..241, BF254..255, BF594..595,++
2SC1206(A,B)	Si-N	UHF-L, 45V, 1,7A, PQ=10..12W(770MHz)	55r	Mit	—
2SC1207(A,B)	Si-N	UHF-L, 45V, 3A, PQ=16..23W(770MHz)	55r	Mit	—
2SC1208(A)	Si-N	VHF-L, 36V, 10A, PQ=37..40W(175MHz)	55r	Mit	BLW60, BLY60
2SC1209	Si-N	Uni, 25V, 0,7A, 0,5W, 150MHz	7b	Mit	BC337..338, BC635, BC637, BC639,++
2SC121	Si-N	=2SC120: 130MHz, B=20..75	2a	Nec	BC167, BC182, BC237, BC547, 2N2218++
2SC1210	Si-N	=2SC1209: 45V, 0,3A	7b		BC337, BC635, BC637, BC639,++
2SC1211	Si-N	=2SC1209: 65V, 0,3A	7b		BC337A, BC637, BC639, 2SD667,++
2SC1212	Si-N	NF/S-L, 150V, 1A, 8W, 160MHz	14h	Hit	BD137, BD228, BD375, 2SD1177..1178
2SC1212A	Si-N	=2SC1212: 60V	14h		BD139, BD230, BD379, 2SD1177..1178
2SC1213	Si-N	Uni, 35V, 0,5A, 0,4W, 120MHz	9b,7c	Hit	BC337..338, BC635, BC637, BC639,++
2SC1213A	Si-N	=2SC1213: 50V	9b,7c		BC337, BC635, BC637, BC639,++
2SC1214	Si-N	Uni, 50V, 0,5A, 0,6W, 50MHz	9b,7c	Hit	BC337, BC635, BC637, BC639,++
2SC1215(S,T)	Si-N	VHF, 30V, 50mA, 1200MHz	7c	Mat	BF377..378, BF689, BF763, 2N2857,++

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2SC1216	Si-N	S, 40V, 0,2A, 0,3W, <20/40ns	2a	Nec	BSS11, BSX19..20, 2N2368..69(A), ++
2SC1217	Si-N	S, Vid, 150V, 0,3A, 0,75W, 250MHz	2a	Nec	BSS43, BSW68, 2SD413, 2SD576, 2SD624
2SC1218	Si-N	NF/S, 80V, 0,5A, 0,75W, 370MHz	2a	Nec	BSW39, 2N3444, 2N3723, 2SC1069
2SC1219	Si-N	Uni, 30V, 0,5A, 0,2W, 60MHz	7c	Fui	BC337..338, BC635, BC637, BC639, ++
2SC122	Si-N	=2SC120: 160MHz, B=50..150	2a	Nec	BC167, BC182, BC237, BC547, 2N2219++
2SC1220	Si-N	=2SC1219: 50V	7c		BC337A, BC637, 2SC3939, 2SD1226, ++
2SC1222	Si-N	Uni, ra, 50V, 0,02A, 0,25W, >30MHz	7c	Nec	BC184, BC414, BC550, 2SC2390, ++
2SC1223	Si-N	VHF/UHF-A/Tr, 30V, 0,5A, 0,8W, 1300MHz	2a	Mit	BFS50, MRF515, 2N3948, 2SC2852
2SC1224	Si-N	NF/S-L, 130V, 0,8A, 7W	13n	Mit	(2SC2483)
2SC1226(A)	Si-N	NF/S-L, 40..50V, 2A, 10W, 150MHz	13j	Mat	2SC1848, (BD507, BD515, BD525, ++)
2SC1227	Si-N	S-L, 300/200V, 10A, 100W, 27MHz	23a	Fui	BUW24, BUW72, BUX17A..C, BUY18, ++
2SC1228	Si-N	S-L, 500/400V, 10A, 100W, 15MHz	23a	Fui	BUW25, BUW34, BUW75, 2SC3043, ++
2SC1229	Si-N	=2SC1227: 250/200V	23a		BUW24, BUW72, BUX17(A..C), BUY18, ++
2SC123	Si-N	=2SC120: 180MHz, B=80..200	2a	Nec	BC167, BC182, BC237, BC547, 2N2219++
2SC1230	Si-N	=2SC1228: 450/400V	23a		BUW24..25, BUW72, BUW75, 2SC3043, ++
2SC1231	Si-N	SS, 20V, 0,2A, 0,3W, <-/27ns	2a	Fui	BSS11..12, BSY17..18, 2N3011, ++
2SC1232	Si-N	UHF-L, 45V, 1A, PQ=6W(770MHz)	55r	Fui	—
2SC1233	Si-N	UHF-L, 45V, 2A, PQ=11W(770MHz)	55r	Fui	—
2SC1235	Si-N	NF-L, Vid-L, 300V, 0,1A, 6,5W(Tc=70°)	22a	Say	2SC1505..1507, 2SC1755..1757, 2SC1819
2SC1236	Si-N	UHF, ra, 20V, 0,03A, 0,2W, 6,5GHz	24d	Tos	BFQ57..58, BFQ74
2SC1237	Si-N	AM-L, 85V, 2A, PQ=3,5W(27MHz)	17j	Tos	2SC1306, 2SC1678..1679, 2SC1909, ++
2SC1236	Si-N	UHF-A/Tr, 35V, 0,15A, 5W, 1700MHz	55r	Mit	BLV90, MRF838A
2SC1239	Si-N	AM-Tr/E, 90V, 4A, PQ=3,4W(27MHz)	43m	Mit	(28C1306, 2SC1909, 2SC2078, 2SC2092, ++)
2SC124	Si-N	=2SC120: 200MHz, B>20	2a	Nec	BC167, BC182, BC237, BC547, 2N2218++
2SC1240	Si-N	HF, 40V, 0,05A, 0,35W, 600MHz	7b	Mit	BF198..199, BF224..225, BF310..311, ++
2SC1241	Si-N	VHF-L, 40V, 1,5A, PQ>6W(175MHz)	55r	Tos	BLW19, BLW37, MRF212, 2N5590
2SC1241A	Si-N	=2SC1241: 35V, 2A, PQ>8W(175MHz)	55r		BLW19, BLW37, MRF212, 2N5590
2SC1242	Si-N	VHF-L, 40V, 3A, PQ>13W(175MHz)	55r	Tos	BLY89, MRF209, 2N5591, 2N6082
2SC1242A	Si-N	=2SC1242: 35V, 4,5A	55r		BLY89, MRF209, 2N5591, 2N6082
2SC1243	Si-N	NF/S-L, 25V, 1,5A, 7W, 70MHz	13n	Mit	(BD429, BD505, BD515, BD839, ++)
2SC1244	Si-N	Uni, S, 30V, 0,05A, 0,2W	7b	Mit	BC168, BC183, BC236, BC548, ++
2SC1246(A)	Si-N	Uni, 30V, 0,5A, 0,4W, 60MHz	7c	Fui	BC337..338, BC835, BC637, BC839, ++
2SC1247(A)	Si-N	=2SC1246: 50V	7c		BC337, BC637, BC639, 2SD1226, ++
2SC1248	Si-N	UHF, ra, 20V, 0,03A, 2,5GHz	51r	Nec	BFQ59, BFQ70, BFR34, BFT97
2SC1249	Si-N	UHF-Tr/E, 45V, 0,3A, 1,7GHz	55r	Nec	BFQ68, 2SC1043, 2SC1251
2SC1250	Si-N	=2SC1249: 1,9GHz	55r		BFQ68, 2SC1043, 2SC1251
2SC1251	Si-N	UHF-A/Tr/E, 45V, 0,3A, 7W, 2,2GHz	55s	Nec	BFQ68, 2SC1043, 2SC1250
2SC1252	Si-N	UHF-A/Tr, 45V, 0,3A, 0,8W, 1,7GHz	2a	Nec	2SC1199, 2SC2852
2SC1253	Si-N	UHF-A/Tr, 45V, 0,3A, 0,8W, 2GHz	2a	Nec	2SC1199, 2SC2852
2SC1254	Si-N	VHF/UHF, 1000MHz	5q	Nec	BF377..378, BF689, BF763, 2N2857, ++
2SC1255	Si-N	UHF-A/Tr/E, 30V, 0,1A, 3,5W, 2,7GHz	55s	Nec	BFQ34, BFR94, 2SC1592
2SC1256	Si-N	VHF/UHF-Tr/E, 36V, 0,8A, PQ=3W(175MHz)	2a	Nec	BFQ43, BFS22, BLY33, MRF237
2SC1257	Si-N	VHF/UHF-L, 36V, 1,5A, PQ=8W(175MHz)	55s	Nec	BLW19, BLW37, MRF212, 2N5590
2SC1256	Si-N	VHF/UHF-L, 36V, 3A, PQ=14W(175MHz)	55s	Nec	BLY89, MRF209, 2N5591, 2N6082
2SC1259	Si-N	VHF/UHF-L, 36V, 6A, PQ=30W(175MHz)	55s	Nec	BLW20, BLW31, 2N6084
2SC125[Hitachi]	Ge-N	VHF/UHF, 20V, 10mA, 700MHz	1g	Hit	—
2SC125[Sony]	Si-N	HF/S, 100V, 0,05A, 0,75W, 200MHz	2a	Son	BF257..259, 2SC1890A, 2SC3245, 2SD755++
2SC128	Si-N	=2SC125[Sony]: 140V	2a	Son	BF257..259, 28C2375, 2SC3245A, 2SD758A++
2SC1280	Si-N	UHF-A/Tr, 45V, 0,03A, 0,25W, 2GHz	5q	Nec	BFR37, BFW30, BFX73
2SC1261	Si-N	UHF, ra, 20V, 0,03A, 0,3W, 2,5GHz	51r	Fui	BFQ59, BFR34, BFT97
2SC1262	Si-N	UHF-Tr/E, 45V, 0,3A, 1,7GHz	55r	Fui	BFQ68, 2SC1043, 2SC1249..1251
2SC1283	Si-N	=2SC1262: 1,9GHz	55r		BFQ68, 2SC1043, 2SC1250..1251
2SC1264	Si-N	UHF-A/Tr, 30V, 0,1A, 0,4W, 2GHz	51r	Fui	BFG34, BFT12
2SC1265	Si-N	Dual, 20V, 0,05A, 0,6W, 3GHz		Nec	—
2SC1266	Si-N	S, 100V, 1,5A, 150MHz, <63/210ns	2a	Nec	(BD139, BD529, BD843, 2SC2275, ++)
2SC1267	Si-N	UHF-A/Tr, 45V, 0,3A, 7W, 2,2GHz	55s	Nec	BFQ68, 2SC1043, 2SC1250..1251
2SC1268	Si-N	UHF, 20V, 0,03A, 0,2W, 6GHz	51s	Nec	BFG91, BFQ57..58, BFQ74, 2SC3276
2SC1269	Si-N	UHF, 20V, 0,03A, 0,2W, 6GHz	51s	Nec	BFG91, BFQ57..58, BFQ74, 2SC3276
2SC127	Si-N	HF-VM/O, 20V, 25mA, 200MHz	2a	Nec	BF240..241, BF254..255, BF594..595, ++
2SC1270	Si-N	UHF, 20V, 0,03A, 0,2W, 6GHz	51s	Nec	BFG91, BFQ57..56, BFQ74, 2SC3276
2SC1271(A)	Si-N	UHF, 20V, 0,03A, 0,2W, 6GHz	51s	Nec	BFG91, BFQ57..56, BFQ74, 2SC3276
2SC1272	Si-N	UHF, 20V, 0,1A, 4GHz	51s	Nec	BFG96, BFP96, BFQ73, BFR96
2SC1273	Si-N	UHF, 20V, 0,1A, 4GHz	51s	Nec	BFG96, BFP96, BFQ73, BFR96
2SC1274	Si-N	S, 40V, 0,3A, 0,3W, <80/86ns	2a	Nec	BSS10, BSX19..20, BSX28, 2N3261
2SC1275	Si-N	UHF, ra, 30V, 25mA, 2GHz	5q	Nec	BF630, BFR15, BFS55, BFW99
2SC1276	Si-N	S, 40V, 0,1A, 0,2W, <20/40ns	7c	Nec	BSV91..92, BSX92..93, 2N2368..69(A), ++

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2SC1277	Si-N	Uni,60V,0,5A,0,25W,60MHz	7c	Nec	BC337A, BC637, 2SC3939, 2SD1226,++
2SC1278	Si-N	Nix,150V,0,05A,0,25W,150MHz	7c	Nec	BF297..299, BF422, BFR87..89,++
2SC1279	Si-N	=2SC1278: 160V	7c		BF297..299, BF422, BFR88..89,++
2SC128	Ge-N	S,30V,0,2A,0,15W,7MHz,<320/1300ns	2a	Mat	ASY28..29, ASY73..75
2SC1280	Si-N-Darl	Uni,15V,0,3A,0,25W,B>5000	7c	Nec	BC517, BC817, BC875, MPS-A13..14,++
2SC1280A	Si-N-Darl	=2SC1260: 30V, B>12000	7c(C)		BC517, BC617, BC875, MPS-A25..26,++
2SC1281	Si-N	Uni,20V,0,02A,0,3W,120MHz	2a	Oki	BC188, BC183, BC239, BC548,++
2SC1282	Si-N	=2SC1282: 70V	2a		BC174, BC546, 2SC1890(A), 2SC2240,++
2SC1283	Si-N	=2SC1261: 110V	2a		2SC1775A, 2SC1690A, 2SC2240, 2SC2363,++
2SC1284	Si-N	UHF,700MHz	7c	Say	BF377..376, BF689, BF783, 2N2857,++
2SC1285	Si-N	Uni,40V,0,1A,0,2W,140MHz	7c	Say	BC187, BC183, BC237, BC547,++
2SC1286	Si-N	TV-ZF,400MHz	7c	Say	BF186..199, BF224..225, BF310..311,++
2SC1288	Si-N	SS,7V,0,06A,0,2W,4,5GHz	24f	Oki	—
2SC129	Ge-N	S,25V,0,2A,0,15W,10MHz,<265/1300ns	2a	Mat	ASY2S..29, ASY73..75
2SC1290	Si-N	UHF-A,40V,0,2A,0,75W,1,5GHz	2a	Oki	BFR36, 2SC1199, 2SC1252
2SC1292	Si-N	S-L,300V,2,5A,60W	23a	Mit	BU126, BUW71, TIP51..54, 2SD632,++
2SC1293	Si-N	HF,400MHz	7c	Say, Mic	BF198..199, BF224..225, BF310..311,++
2SC1295	Si-N	TV-HA,1000V,2A,40W	23a	Say	BU204..206, 2SC1132, 2SD1097..1098,++
2SC1298	Si-N	TV-HA,1300V,5A,50W	23a	Say	BU207..209, 2SC2928, 2SD350, 2SD820,++
2SC1297	Si-N	VHF-L,50V,3,5A,PQ=26W(175MHz)	55s	Nec	MRF314A..315A, 2SC2888
2SC1286	Si-N	VHF-L,50V,5A,PQ=37W(175MHz)	55s	Nec	BLW25, BLY94, 2N5843, 2SC2689
2SC1299	Si-N	S-L,300V,30A,200W,25MHz	68a	Fui	2SC1401, 2SC1873, 2SD542..543, 2SD643,++
2SC13	Ge-N	NF/S,18V,0,04A,0,095W,>3,5MHz	2a	Tos	AC127, ASY2S..29
2SC130	Si-N	HF/S-L,60V,1A,20W,160MHz	2a	Fui	(BD137, BD228, 2SC1398, 2SC3252,++)
2SC1300	Si-N	S-L,500V,30A,200W,20MHz	68a	Fui	2SC1874, 2SC2220, 2SC2442, 2SC2444,++
2SC1301	Si-N	=2SC1301: 250V	88a		2SC1873, 2SC2249, 2SC2445, 2SD643,++
2SC1302	Si-N	=2SC1301: 400V	88a		2SC1401, 2SC1470, 2SC2250, 2SD542..43,++
2SC1303	Si-N	VHF-Tr/E,40V,0,3A,PQ=0,6W(175MHz)	2a	Mat	BFX55, MRF207, MRF807
2SC1304	Si-N	NF-L,300V,0,5A,20W,7MHz	22a	Hit	2N3739, 2SC782, 2SC1929, 2SC2354,++
2SC1306	Si-N	HF-L,65V,3A(ss),PQ=5,5W(50MHz)	17j	Nec	—
2SC1307	Si-N	HF-L,70V,8A(ss),PQ=15W(50MHz)	17j	Nec	—
2SC1306	Si-N	TV-HA,1500/400V,7A,50W	23a	Say	BU508(A), 2SC3027..26, 2SD822, 2SD1018
2SC1309	Si-N	TV-VA,1200V,5A,80W	23a	Mit	2SC1413, 2SD1099, 2SD1103
2SC131	Si-N	S,40V,0,3A,0,35W,350MHz,-/40ns	2a	Fui	BSS10, BSX19..20, BSX26, 2N3261,++
2SC1310	Si-N	Uni,ra,50V,0,2A,0.3W,200MHz	41c	Mit	BC414, BC550, 2SC2240, 2SC3112..13,++
2SC1311	Si-N	=2SC1310. AM/FM	41c		BF240..241, BF254..255, BF594..595,++
2SC1312	Si-N	Uni,ra,35V,0,1A,0,2W,150MHz	7b	Mit	BC169, BC184, BC239, BC549,++
2SC1313	Si-N	=2SC1312: 50V	7b		BC184, BC414, BC550, 2SC2240,++
2SC1314(A)	Si-N	VHF-L,40V,5A,PQ=34W(175MHz)	55r	Mit	BLW20, BLW31, 2N6084
2SC1315	Si-N	VHF-Tr/E,35V,0,5A,PQ=0,5W(150MHz)	2a	Mit	BFR98, BLW16, BLY61, MRF225,++
2SC1316	Si-N	S-L,750V,2A,23W,8,5MHz	22a	Son	BUV36(A), BUX84..85, 2SC3149, 2SC3352
2SC1317	Si-N	Uni,30V,0,5A,0,625W,200MHz	7c	Mat,Mic	BC337..338, BC635, BC837, BC639,++
2SC1318	Si-N	=2SC1317: 60V	7c		BC337A, BC637, BC639, 2SD667,++
2SC1318A	Si-N	=2SC1351: 60V	7c		BC639, 2SD667, 2SD1226, 2SD1788,++
2SC1319	Si-N	HF/ZF,re,600MHz	7c	Nec	BF198, BF225, BF310, BF367, BF596++
2SC132	Si-N	S,20V,0,3A,0,35W,350MHz,-/40ns	2a	Fui	BSS10, BSX19..20, BSX26, 2N3261,++
2SC1320	Si-N	HF/ZF,850MHz	7c		BF199, BF224, BF311, BF373, BF597++
2SC1321	Si-N	SMD,UHF,900MHz	35a	Nec	BFS17, 2SC3005, 2SC3018, 2SC3161
2SC1322	Si-N	S-L,250V,15A,100W,27MHz	23a	Fui	BUX13, BUX41, 2SD552, 2SD583,++
2SC1323	Si-N	UHF-Tr/E,30V,0,5A,5W,1300MHz	51r	Mit	BLX86, MRF827..828, 2N6256
2SC1324	Si-N	UHF-A/Tr,35V,0,15A,0,8W,1,7GHz	5q	Mit	BFR36, BFW18, 2SC1068
2SC1325(A)	Si-N	CTV-HA,1500/600V,5A,60W	23a	Nec	BU206(A), BU508(A), 2SC2928, 2SD954,++
2SC1326	Si-N	VHF-Tr/E,55V,0,4A,PQ>1W(400MHz)	2a	Mat	BFS23, BFW47, BLY34, 2N3553, 2N5160
2SC1327	Si-N	Uni,ra,35V,0,05A,0,15W,250MHz	7c	Mat,Mic	BC189, BC184, BC239, BC549,++
2SC1328	Si-N	=2SC1327: 55V	7c		BC414, BC550, 2SC2240, 2SC2390,++
2SC1329	Si-N	FM-L,50V,8A,PQ=32W(70MHz)	55s	Nec	2SC2313
2SC133	Si-N	S,20V,0,3A,0,35W,350MHz,-/40ns	2a	Fui	BSS10, BSX19..20, BSX26, 2N3261,++
2SC1330	Si-N	Uni,50V,0,1A,0,4W,250MHz	7c*	Nec,Mic	BC167, BC182, BC237, BC547,++
2SC1331	Si-N	ZF,UHF,750MHz	5q	Nec	BF377..378, BF889, BF783, 2N2857,++
2SC1333	Si-N	UHF-Tr/E,45V,1A,10W,1200MHz	55s	Nec	BLW33..34, 2N4430, 2SC3140
2SC1334	Si-N	UHF-Tr/E,50V,1A,11,6W,1200MHz	55s	Nec	BLW98, BLX98, 2N4431, 2SC3141
2SC1335	Si-N	Uni,ra,30V,0,1A,0,2W,230MHz	9b	Hit	BC189, BC184, BC239, BC549,++
2SC1336	Si-N	UHF,ra,20V,0,03A,0,25W,4,5GHz	51s	Nec	BFQ71, BFQ85, BFR14, 2SC1119
2SC1337(A)	Si-N	UHF-L,35V,2A,PQ=8,5W(485MHz)	55r	Mit	BLW14, BLW44, 2N5646
2SC1338(A)	Si-N	UHF-L,35V,3A,PQ=16W(485MHz)	55r	Mit	BLW15, BLX89
2SC1339	Si-N	UHF-L,35V,5A,PQ=28W(485MHz)	55r	Mit	BLW15, BLX89

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2SC134	Si-N	S, 40V, 0,3A, 0,35W, 350MHz, -/125ns	2a	Fui	BSS10, BSX19..20, BSX26, 2N3261, ++
2SC1340	Si-N	UHF-Tr/E, 35V, 1A, 5W, 1GHz	55r	Mit	BLU97, BLW43, BLW80, BLX68, BLY53
2SC1342	Si-N	FM-VM/O, 320MHz	9b, 7c	Hit	BF240..241, BF254..255, BF594..595, ++
2SC1343	Si-N	NF/S-L, 150V, 10A, 100W, 14MHz	23a	Hit	BD245D, 2SD551, 2SD733, 2SD1047, ++
2SC1344	Si-N	NF, ra, 30V, 0,1A, 0,2W, 230MHz	9b, 7c	Hit	BC169, BC184, BC239, BC549, ++
2SC1345	Si-N	=2SC1344: 55V	9b, 7c		BC414, BC550, 2SC2240, 2SC2459, ++
2SC1346	Si-N	=2SC1317: 0,6W	7c°		→2SC1317
2SC1347	Si-N	=2SC1318: 0,6W	7c°		→2SC1318
2SC1348(-1...-3)	Si-N	TV-HA, 1000..1200V, 4A, 125W, 5MHz	23a	Son	(BU207..209, BU508, 2SC2928, 2SD954++)
2SC1349	Si-N	SS, 20V, 0,2A, 0,2W, -/15ns	2a	Fui	BSS11, BSX19..20, 2N2368..69(A), ++
2SC135	Si-N	S, 20V, 0,3A, 0,35W, 350MHz, -/125ns	2a	Fui	BSS10, BSX19..20, BSX26, 2N3261, ++
2SC1350	Si-N	S, 25V, 0,3A, 0,3W, <-/60ns	2a	Fui	BSS11, BSX19..20, 2N2368..69(A), ++
2SC1351	Si-N	S, 80V, 1A, 0,8W, <50/65ns	2a	Fui	BSV95, 2N3735, 2SC1069
2SC1352	Si-N	S, 25V, 0,8A, 0,6W, <15/20ns	2a	Fui	BSS28..29, BSV69, BSX12, 2N3426, ++
2SC1353	Si-N	S, 90V, 0,7A, 0,65W, 45/95ns	2a	Fui	BSW39, 2SC1069
2SC1354	Si-N	VHF-L, 55V, 5A, PQ=37W(175MHz)	60c	Mat	—
2SC1355	Si-N	UHF-Tr/E, 40V, 0,7A, PQ=2W(700MHz)	55r	Fui	BLU99
2SC1356	Si-N	UHF-Tr/E, 40V, 1A, PQ=6W(700MHz)	55r	Fui	—
2SC1358(A)	Si-N	TV-HA(90°), 1400/500V, 4,5A, 50W	23a	Nec	BU208..209, BU508(A), 2SD763, 2SD954++
2SC1359	Si-N	Uni, 30V, 0,03A, 0,4W, 250MHz	7c	Mat, Mic	BC237, BC548, BF240..241, BF254..255, ++
2SC136	Si-N	S, 80V, 0,3A, 0,35W, 350MHz, -/125ns	2a	Fui	2N4014
2SC1360(A)	Si-N	TV-ZF, 50..80V, 0,05A, 1W, >300MHz	7c(9mm)	Mat	BF370, BF920..921(S), BF959
2SC1361	Si-N	Uni, ra, 25V, 0,2A, 0,25W, 140MHz	7c	Son	BC169, BC184, BC239, BC549, ++
2SC1362	Si-N	=2SC1361: 50V	7c		BC414, BC550, 2SC2240, 2SC2459, ++
2SC1363	Si-N	Uni, 25V, 0,2A, 0,25W, 140MHz	7c	Son	BC168, BC183, BC236, BC548, ++
2SC1364	Si-N	=2SC1363: 50V	7c		BC167, BC182, BC237, BC547, ++
2SC1365	Si-N	UHF-A/Tr, 45V, 0,3A, 0,8W, 1,7GHz	2a	Nec	2SC1199, 2SC1252..1253, 2SC2852
2SC1366	Si-N	=2SC1365: 2GHz	2a		2SC1253, 2SC2852
2SC1367(A)	Si-N	TV-VA, 1000V, 1A, 50W, 6MHz	23a	Hit	BU204..206, 2SC1101, 2SC1167, 2SD1095++
2SC1368	Si-N	NF/S-L, 25V, 1,5A, 8W, 180MHz	14h	Hit	BD135, BD226, BD375, 2SD1380, ++
2SC137	Si-N	S, 25V, 0,3A, 0,35W, 350MHz, -/40ns	2a	Fui	BSS10, BSX19..20, BSX26, 2N3261, ++
2SC1372	Si-N	Uni, 30V, 0,2A, 0,2W, 250MHz	7c	Fui	BC168, BC183, BC236, BC548, ++
2SC1373	Si-N	Uni, 25V, 0,1A, 0,3W, <100/325ns	2a	Hit	BC236, BC548, BSY62..63, 2N706A, ++
2SC1374	Si-N	SS, 25V, 0,1A, 0,3W, <13/16ns	2a	Hit	BSV69..92, BSX92..93, 2N2368..69(A), ++
2SC1375	Si-N	SS, 25V, 0,1A, 0,3W, <45/60ns	2a	Hit	BSV69..92, BSX92..93, 2N2368..69(A), ++
2SC1376	Si-N	SS, 40V, 0,5A, 0,3W, <25/40ns	2a	Hit	BSS10, BSX26, BSX39, 2N3261
2SC1377	Si-N	AM-SSB-L, 90V, 8A, PQ>8W(27MHz)	17j	Tos	2SC1307, 2SC1944, 2SC1969, 2SC2098
2SC1378	Si-N	VHF-L, 40V, 4A, PQ=25W(175MHz)	55r	Tos	BLY69, MRF209, 2N5591, 2N6082,
2SC1379	Si-N	VHF-L, 40V, 7A, PQ=40W(175MHz)	60c	Tos	—
2SC136(A)	Si-N	FM/VHF-A/Tr, 80V, 0,5A, 0,8W, 400MHz	5g	Nec	BFS23, BFX55, BLY34, 2SC2852
2SC1380	Si-N	Uni, 55V, 0,1A, 0,2W, 80MHz	2a	Tos	BC167, BC182, BC237, BC547, ++
2SC1380A	Si-N	=2SC1380: ra	2a		BC414, BC550, 2SC2240, 2SC2459, ++
2SC1381	Si-N	NF/S-L, 100V, 1A, 5W, 50MHz	14h	Tos	BD139, BD230, BD379, 2SC3421, ++
2SC1382	Si-N	NF/S-L, 80V, 0,75A, 5W, 100MHz	14h	Tos	BD139, BD230, BD379, 2SA3421, ++
2SC1383	Si-N	Uni, 30V, 1A, 1W, 200MHz	7c(9mm)	Mat	2SC2238, 2SD863, 2SD1207, 2SD1331, ++
2SC1384	Si-N	=2SC1383: 80V	7c(9mm)		2SC3328, 2SC4145, 2SD863, 2SD1207
2SC1385	Si-N	S, 80V, 0,5A, 0,8W, <40/60ns	2a	Hit	BSS27, BSV77, 2N5199, 2SC1072, ++
2SC1386	Si-N	S, 70V, 1A, 0,8W, <30/55ns	2a	Hit	BSS27, BSV95, 2N3735, 2SC1069, ++
2SC1387	Si-N	UHF, CATV, 25V, 0,15A, 0,5W, 1,6GHz	2a	Fui	BFR36, BFW16, 2SC1068, 2SC1324
2SC1388	Si-N	S, 100V, 1A, 0,8W, <50/110ns	2a	Fui	2SC1069
2SC139	Si-N	=2SC136	5g		BFS23, BFX55, BLY34, 2SC2852
2SC1390	Si-N	Uni, ra, 20V, 0,05A, 0,2W, 230MHz	7c	Hit	BC169, BC184, BC239, BC549, ++
2SC1391	Si-N	Vid-L, 300V, 0,1A, 6,5W, 25MHz	22a	Hit	2SC1505..1507, 2SC1749, 2SC1819, ++
2SC1393	Si-N	VHF-V, ra, 700MHz	7f	Nec	BF225, BF310, BF314, BF502, BF505++
2SC1394	Si-N	VHF-M, 700MHz	7f	Nec	BF224, BF310, BF314, BF505, BF507++
2SC1395	Si-N	VHF-O, >600MHz	7c	Nec	BF377..378, BF689, BF763, 2N2857, ++
2SC1396	Si-N	=2SC1395: >800MHz	7c		BF377..378, BF689, BF763, 2N2857, ++
2SC1398(A)	Si-N	NF/S-L, 70V, 2A, 15W, 120MHz	17j	Mat	2SC2526, 2SC3252
2SC1399	Si-N	Uni, 100V, 0,05A, 0,25W, 100MHz	7c	Nec	2SCS1890A, 2SC2363, 2SC3245, 2SD756(A)++
2SC14	Ge-N	=2SC13: >11MHz	2a	Tos	AC127, ASY28..29
2SC140	Si-N	Uni, 80V, 1A, 1,7W, 150MHz	2a	Son	BC140..141, BCX40, 2N1990, 2N2102, ++
2SC1400	Si-N	=2SC1399: ra	7c		2SC1775A, 2SC2088, 2SC2240, 2SC2459, ++
2SC1401	Si-N	S-L, 400/350V, 30A, 200W, 20MHz	68a	Fui	2SC1302, 2SC1470, 2SC2250, 2SD542..543
2SC1402	Si-N	NF/S-L, 140V, 8A, 70W, 10MHz	23a	Sak	BD245D, 2N3442, 2SD551, 2SD1047, ++
2SC1403	Si-N	=2SC1402: 180V	23a		BD245D, 2N3442, 2SD551, 2SD1047, ++
2SC1403A	Si-N	=2SC1402: 180V	23a		BD245E, BDW16, 2SC2261..62, 2SD751, ++

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2SC1404	Si-N	UHF-L, 36V, 3,5A, PQ=18W(470MHz)	55r	Mat	BLX69, 2SC1338
2SC1405	Si-N	VHF-Tr/E, 36V, 0,75A, PQ=3,5W(175MHz)	51r	Mat	BLW17, 2SC1011
2SC1406	Si-N	Uni, 30V, 1A, 1W, 200MHz	7c°	Mat	BC337..338, BC635, BC637, BC639, ++
2SC1407	Si-N	=2SC1406: 60V	7c°		BC337A, BC637, BC639, 2SD667, ++
2SC1409(A)	Si-N	NF-L, 200V, 2A, 12,5W, 20MHz	17j	Hit	BD239F, 2SC2660, 2SD760, 2SD1138, ++
2SC141	Si-N	HF/S, 20V, 0,2A, 0,36W, 450MHz	2a	Oki	BSS11, 2N2368..69(A), 2SC2901, 2SC3732
2SC1410(A)	Si-N	NF-L, 200V, 2A, 12,5W, 20MHz	17j		BD239F, 2SC2660, 2SD760, 2SD1136, ++
2SC1411	Si-N	Chopper, 6V, 0,05A, 0,2W	2a		—
2SC1412	Si-N	UHF-A/Tr, 45V, 0,15A, 0,6W, 1,5GHz	2a	Fui	BFR36, BFW16, 2SC1068, 2SC1324
2SC1413	Si-N	TV-HA, 1200/500V, 5A, 50W, 4MHz	23a	Hit	BU207..209, BU508, 2SD1099, 2SD1103, ++
2SC1413A	Si-N	=2SC1413: 1500/500V	23a		BU208..209, BU508, 2SC2928, 2SD954, ++
2SC1414	Si-N	UHF-L, 40V, 2A, PQ=10W(700MHz)	55r	Fui	2SC1067
2SC1415	Si-N	UHF-L, 40V, 3A, PQ=16W(700MHz)	55r	Fui	2SC1087
2SC1416(A)	Si-N	Uni, ra, 55V, 0,05A, 0,2W, 100MHz	2a	Tos	BC414, BC550, 2SC2240, 2SC2390, ++
2SC1417	Si-N	HF, 20V, 0,03A, 300MHz	9b	Hit	BF240..241, BF254..255, BF594..595, ++
2SC1418	Si-N	NF/S-L, 50V, 2A, 20W, 5MHz	17j	Hit	BD239, 2SC1398, 2SC2528, 2SC3252, ++
2SC1419	Si-N	=2SC1418	17j		BD239, 2SC1398, 2SC2528, 2SC3252, ++
2SC142	Si-N	HF/S, 30V, 0,2A, 0,36W, 28/42ns	2a	Oki	BSS11, 2N2368..69(A), 2SC2901, 2SC3732
2SC1420	Si-N	UHF, 15V, 0,07A, 0,3W, 6GHz	51r	Fui	2SC2876, 2SC3603
2SC1421	Si-N	UHF, 15V, 0,03A, 0,25W, 5,5GHz	51r	Fui	BFG91, BFP91, BFQ57..58, BFQ74
2SC1422	Si-N	UHF, 15V, 0,04A, 0,25W, 5,5GHz	51r	Fui	BFG91, BFP91, BFQ57..58, BFQ74
2SC1423	Si-N	UHF, 15V, 0,03A, 0,25W, 7GHz	51r	Fui	BFG65, BFQ66, 2SC3062, 2SC3276,
2SC1424	Si-N	VHF/UHF-V, ra, 2GHz	5g	Nec	BF377..378, BFR37, BFS55, BFW30, ++
2SC1425	Si-N	UHF-Tr/E, 45V, 1A, PQ=3W(1GHz)	55s	Nec	2N4430
2SC1426	Si-N	UHF-A/Tr, 35V, 0,2A, 2,7GHz	5g	Nec	—
2SC1427	Si-N	SMD, UHF, 1GHz	35a	Nec	BFS17, 2SC3005, 2SC3016, 2SC3161
2SC1428	Si-N	SMD, Uni, 50V, 0,05A, 250MHz	35a	Nip	BC846..847, BCW71..72, BCW81, ++
2SC1429-	Si-N	NF/HF/S, 12..16V, 2A, 80MHz	13m	Son	BC365, BD505, BD515, BD525, ++
2SC143	Si-N	HF/S, 40V, 0,2A, 0,36W, 28/42ns	2a	Oki	BSS11, 2N2368..69(A), 2SC2901, 2SC3732
2SC1430-1	Si-N	NF/S, 110V, 1,5A, 0,5W, 50MHz	2a	Son	BCX40, BSS42..43, BSW67..68, BSX47
2SC1430-2	Si-N	=2SC1430-1: 140V	2a		BSS43, BSW68, 2SC1660
2SC1431-1	Si-N	NF/S-L, 110V, 2A, 23W, 80MHz	22a	Son	2SC2528..2529
2SC1431-2	Si-N	=2SC1431-1: 140V	22a		2SC2529
2SC1432	Si-N-Darl	Uni, 30V, 0,3A, 0,3W, B=40000	7c	Njr	BC517, BC875, MPS-A13..14, 2SD892, ++
2SC1433	Si-N	S-L, 600V, 5A, 50W	23a	Tos	BUW25, BUX82, 2SC2962, 2SD640, ++
2SC1434	Si-N	S-L, 600/400V, 15A, 150W	23a	Tos	BUS13, BUW45..46, BUX48, 2SD841, ++
2SC1435	Si-N	S-L, 600V, 40A, 300W	68a	Tos	2SD842
2SC1436	Si-N	S-L, 230V, 15A, 100W, 10MHz	23a	Sak	BUW50..52, BUX41, BUX70, 2SD583, ++
2SC1437	Si-N	=2SC1436: 50A, 200W	68a		2SC2147, 2SC2159, 2SC2942
2SC1436	Si-N	Vid, 150/120V, 0,05A, 0,5W, 130MHz	7c	Fui	BF297..299, BF422, BFR87..69, ++
2SC1439	Si-N	=2SC1438: 150/150V	7c		BF297..299, BF422, BFR87..69, ++
2SC144(A)	Si-N	HF/S, 50(A=60)V, 0,2A, 0,36W, 28/47ns	2a	Oki	2SC1834
2SC1440	Si-N	S-L, 150/150V, 15A, 100W, 10MHz	23a	Sak	BD745E, BUX41, 2SC1584, 2SD552, ++
2SC1441	Si-N	=2SC1440: 200V	23a		BDW16, BUX41, 2SC1585, 2SD552, ++
2SC1442	Si-N	=2SC1440: 50A, 200W	68a		2SC1437, 2SC2147, 2SC2159, 2SC2942
2SC1443	Si-N	=2SC1440: 200V, 50A, 200W	68a		2SC1437, 2SC2147, 2SC2159, 2SC2942
2SC1444	Si-N	NF/S-L, 60V, 6A, 40W, 10MHz	22a	Sak	BD243B, BD543B, BD799, 2N5427..28, ++
2SC1445	Si-N	=2SC1444: 100V	22a		BD243C, BD543C, BD801, 2N5429..30, ++
2SC1446	Si-N	NF/Vid-L, 300V, 0,1A, 10W(Tc=70°)	17j	Mat	2SC1505..1507, 2SC1755..1757, 2SC1905, ++
2SC1447	Si-N	NF/Vid-L, 300V, 0,15A, 20W, 80MHz	17j	Tos	2SC1505..1507, 2SC1755..1757, 2SC1905, ++
2SC1448(A)	Si-N	NF/S-L, 150V, 1,5A, 25W, 5MHz	17j	Tos	BD239D, 2SC2073, 2SD608(A), 2SD1138, ++
2SC1449	Si-N	NF-E, 40V, 2A, 5W, 50MHz	14h	Nec	BD375, 2SC3422, 2SD1380, 2SD1818, ++
2SC145	Si-N	HF/S, 30V, 0,2A, 0,36W, 500MHz	2a	Oki	BSS11, 2N2368..69(A), 2SC2901, 2SC3732
2SC1450(S)	Si-N	NF/S-L, 150V, 0,4A, 20W(Tc=80°)	22a	Mat	BD239D, 2SC2073, 2SD808, 2SD1138, ++
2SC1451	Si-N	S/Vid, 150/120V, 0,05A, 0,7W, 130MHz	2a°	Fui	BF257..258, BF657..659, 2N5058..59
2SC1452	Si-N	=2SC1451: 150/150V	2a°		BF257..258, BF657..659, 2N5058..59
2SC1453	Si-N	Uni, 55V, 0,1A, 0,2W, 150MHz	2a	Tos	BC167, BC182, BC237, BC547, ++
2SC1454	Si-N	S-L, 300V, 4A, 50W, 10MHz	23a	Sak	BU606..608, BUW71, 2SC2624, 2SD632, ++
2SC1456	Si-N	Vid-L, 300V, 0,2A, 15W, 80MHz	22a	Nec	2SC1505..1507, 2SC1755..1757, 2SC1905
2SC1457	Si-N	UHF-A/Tr, ra, 35V, 0,15A, 0,8W, 2,7GHz	5g	Nec	BFR95
2SC1458	Si-N	UHF, 20V, 0,05A, 0,3W, 3GHz	51s	Nec	BFQ72, 2SC2844, 2SC3302
2SC1459	Si-N	=2SC1420	51r	Fui	→2SC1420
2SC146(A)	Si-N	HF/S, 50(A=60)V, 0,2A, 0,36W, 500MHz	2a	Oki	2SC1834
2SC1460	Si-N	=2SC1421	51r	Fui	→2SC1421
2SC1461	Si-N	=2SC1422	51r	Fui	→2SC1422
2SC1462	Si-N	=2SC1423	51r	Fui	→2SC1423

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2SC1463	Si-N	S-L, 450V, 4A, 75W, 25MHz	23a	Fui	BUW71, BUX45, 2SC2624, 2SC3083, ++
2SC1464	Si-N	VHF-Tr/E, 50V, 0,5A, PQ=1,2W(175MHz)	2a	Fui	BFR98, BFS23, BLW16, BLY34, BLY61
2SC1465	Si-N	UHF-Tr/E, 50V, 0,5A, PQ=1,8W(700MHz)	51r	Fui	—
2SC1466	Si-N	S-L, 450/360V, 3A, 30W, 10MHz	22a	Shi	BUT93, BUY63..64, TIP75B, 2SC2929, ++
2SC1467	Si-N	=2SC1466: 500/400V	22a		BUT93, BUY63..64, TIP75C, 2SC2828, ++
2SC1468	Si-N	S-L, 450/360V, 10A, 100W, 10MHz	23a	Shi	BUW24..26, BUW34..36, BUY69..70, ++
2SC1469(A)	Si-N	=2SC1468: 500/400V	23a		BUW25..26, BUW34..36, BUY69..70, ++
2SC147	Si-N	Uni, 30V, 1A, 0,75W, 120MHz	2a	Son	BC140..141, BCX40, 2N1990, 2N2102, ++
2SC1470	Si-N	S-L, 450/360V, 30A, 200W, 10MHz	68a	Shi	2SC1300, 2SC1874, 2SC2220, 2SC2444, ++
2SC1471(A)	Si-N	=2SC1470: 500/400V	68a		2SC1300, 2SC1874, 2SC2220, 2SC2444, ++
2SC1472	Si-N-Darl	Uni, 30V, 0,3A, 0,5W, >50MHz, B>2000	5c(C)	Hit	BC517, BC617, BC675, MPS-A25..29, ++
2SC1473(NC)	Si-N	Vid, 250/200V, 0,07A, 0,75W, 80MHz	7c	Mat	BF298..299, BF422, BFR66..69, ++
2SC1473A	Si-N	=2SC1473: 300/300V	7c		BF299, BF420, BFR69, 2SC3466, ++
2SC1474-	Si-N	Uni, 20V, 2A, 0,75W, 80MHz	7c(9mm)	Son	2SD787..788, 2SD1100, 2SD1146, 2SD1207++
2SC1475-	Si-N	Uni, 100V, 1A, 0,75W, 80MHz	7c(9mm)	Son	2SC3326, 2SD667, 2SD1292, 2SD1612, ++
2SC1476	Si-N	UHF-L, 36V, 5A, PQ=26W(470MHz)	55r	Tos	2SC1339
2SC1477	Si-N	S-L, 230V, 9A, 80W, 10MHz	23a	Sak	BUX17(A..C), BUY18, TIP180..162, ++
2SC1476	Si-N	Uni, 35V, 0,05A, 0,15W, 150MHz	~2b	Mat	BC166, BC183, BC236, BC548, ++
2SC1476A	Si-N	=2SC1478: 55V	~2b		BC167, BC162, BC237, BC547, ++
2SC1479	Si-N	VHF-Tr/E, 36V, 0,5A, PQ=1,2W(175MHz)	2a	Fui	BFR98, BFS51, BFQ42, BLW16, BLY61
2SC1460	Si-N	UHF-Tr/E, 36V, 0,5A, PQ=2,4W(470MHz)	55r	Fui	BLW79, BLX67, BLY36, 2N5945
2SC1461	Si-N	UHF-L, 36V, 1A, PQ=5W(470MHz)	55r	Fui	BLW43, BLW80
2SC1462	Si-N	UHF-L, 36V, 2A, PQ=8,5W(470MHz)	55r	Fui	BLW44, 2N5946, 2SC1337
2SC1482A	Si-N	=2SC1462: 2,5A, PQ=15W(470MHz)	55r		BLW15, BLX69, 2SC1338
2SC1463	Si-N	UHF, ra, 20V, 0,04A, 3GHz	51r	Fui	BFQ59, BFQ70, BFR34, BFT97
2SC1464	Si-N	UHF-Tr/E, 45V, 0,3A, 5W, 2GHz	55r	Fui	BFR65, 2SC1043, 2SC1250..1251
2SC1485	Si-N	S/Vid, 250V, 0,125A, 0,35W	2a	Fui	BF298..299, BF422A, BFR88..69, ++
2SC1466	Si-N	=2N5944		Mot	→2N5944
2SC1487	Si-N	=2N5945		Mot	→2N5945
2SC1468	Si-N	=2N5946		Mot	→2N5946
2SC1469	Si-N	=2N6136		Mot	→2N6136
2SC149	Si-N	VHF/S, 120V, 0,3A, 0,8W, 180MHz	2a	Nec	BC300, 2N1693(A), 2SD413, 2SD624
2SC1490	Si-N	=2N6080		Mot	→2N6080
2SC1491	Si-N	=2N6061		Mot	→2N6081
2SC1492	Si-N	=2N6062		Mot	→2N6082
2SC1493	Si-N	=2N6083		Mot	→2N6083
2SC1494	Si-N	=2N6084		Mot	→2N6084
2SC1495	Si-N	=2N8256		Mot	→2N6256
2SC1498	Si-N	UHF-L, 36V, 2,5A, 45W	57s	Mot	BLU20/12, MRF641
2SC1499	Si-N	UHF-L, 36V, 6A, 115W	57s	Mot	BLU30/12, MRF644
2SC15-0	Si-N	Uni, 30V, 0,05A, 0,75W, 150MHz	2a	Son	BC163, BC236, BC546, 2N2216..19, ++
2SC15-1	Si-N	=2SC15-0: 80V	2a		BC182, BC190, BC546, 2N2218..19, ++
2SC15-2	Si-N	=2SC15-0: 90V	2a		2SC1690(A), 2SC2240, 2SD755..756(A), ++
2SC15-3	Si-N	=2SC15-0: 120V	2a		2SC1890A, 2SC2240, 2SD756(A), ++
2SC150(H)	Si-N	Uni, 20V, 0,1A, 0,75W, 100MHz	2a	Hit	BC166, BC183, BC238, BC546, 2N2218++
2SC1500	Si-N	UHF-L, 36V, 8A, 115W	57s	Mot	BLU45/12, BLW82, MRF646
2SC1501	Si-N	Vid-L, 300V, 0,1A, 10W, 55MHz	14h	Mat	BF417, BF459, 2SC3417, 2SC3503
2SC1503	Si-N	VHF/UHF-L, 50V, 3A, PQ=13W(280MHz)	55r	Tos	BLW94, BLX94, MRF323, 2SC1118
2SC1504	Si-N	S-L, 400/300V, 2A, 40W, 10MHz	22a	Sak	BUX67C, 2N3565, 2N4240, 2SC3055, ++
2SC1505	Si-N	Vid-L, 300V, 0,2A, 15W, 80MHz	17j	Nec	2SC1755..1757, 2SC1905
2SC1508	Si-N	=2SC1505	17j		2SC1755..1757, 2SC1905
2SC1507	Si-N	=2SC1505	17j		2SC1755..1757, 2SC1905
2SC1509(NC,Z)	Si-N	Uni, 80V, 0,5A, 1W, 120MHz	7c(9mm)	Mat	2SC3939, 2SC3328, 2SD667, 2SD1812, ++
2SC150T	Si-N	=2SC150: 50V	2a		BC167, BC182, BC237, BC547, 2N2218++
2SC151(H)	Si-N	Uni, 40V, 0,2A, 0,75W, 130MHz	2a	Hit	BC167, BC182, BC237, BC547, 2N2218++
2SC1510	Si-N	UHF-L, 47V, 1A, PQ=4,5W(770MHz)	55r	Mit	BLW96, BLX98, 2N4431
2SC1511	Si-N	VHF/UHF-L, 50V, 3A, PQ=25W(275MHz)	67s	Nec	MRF325..326
2SC1512	Si-N	VHF/UHF-L, 50V, 5A, PQ=37W(275MHz)	57s	Nec	2N6439, 2SC2796, 2SC2895
2SC1513	Si-N	VHF/UHF-Tr/E, 40V, 0,3A, 1,8GHz	5g	Hit	2SC1199, 2SC1252, 2SC1365..1366
2SC1514	Si-N	Vid-L, 300V, 0,1A, 80MHz	17j	Hit	2SC1505..1507, 2SC1755..1757, 2SC1905
2SC1515	Si-N	Vid, 200V, 0,05A, 0,2W, 110MHz	9b, 7c	Hit	BF298..299, BF422, BFR66..89, ++
2SC1518	Si-N	NF/S-L, 35V, 1,5A, 10W, 110MHz	17j	Hit	2SC1398, 2SC2275, 2SC2528, 2SC3252
2SC1517	Si-N	NF/S-L, 50V, 1A, 10W, 150MHz	17j	Hit	2SC1398, 2SC2275, 2SC2526, 2SC3252
2SC1517A	Si-N	=2SC1517: 80V	17j		2SC1398, 2SC2275, 2SC2528, 2SC3252
2SC1518(NC)	Si-N	DC-DC-Conv., 25V, 1A, 1W, 150MHz	7c(9mm)	Mat	2SC2236, 2SD863, 2SD1207, 2SD1331, ++
2SC1519	Si-N	Vid-L, 250V, 0,2A, 10W, 80MHz	13j	Nec	(BF615, BF617, BF858..859, 2SC1758, ++)

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2SC152(H)	Si-N	Uni, 60V, 0,2A, 0,75W, 160MHz	2a	Hit	BC174, BC182, BC190, BC548, 2N2218++
2SC1520-..	Si-N	Vid-L, 250..300V, 0,2A, 12,5W, 80MHz	13j	Nec	(BF617, BF859, BF758, MPS-U10,++)
2SC1521	Si-N	=2SC1520	13j		→2SC1520
2SC1522	Si-N	=2SC1519:	≈13j		→2SC1519
2SC1523	Si-N	VHF/UHF-Tr/E, 40V, 0,3A, 2GHz	55r	Hit	BFQ41, MRF826, 2N5944
2SC1524	Si-N	UHF-L, 50V, 1A, PQ=8W(700MHz)	55r	Fui	—
2SC1525	Si-N	UHF-L, 50V, 2A, PQ=13W(700MHz)	55r	Fui	2SC1087
2SC1526	Si-N	UHF-L, 50V, 3A, PQ=22W(700MHz)	55r	Fui	—
2SC1528	Si-N	VHF-L, 40V, 2,5A, PQ=16W(175MHz)	25r	Mit	—
2SC1529	Si-N	UHF-A, 30V, 0,02A	5g	Mit	BF689, BFX62, BFX89, BFR37, BFW30++
2SC153	Si-N	Uni, 120V, 0,2A, 0,75W, 140MHz	2a	Hit	2SC2240, 2SC2459, 2SC3245(A), 2SC3248
2SC1530	Si-N	UHF-Tr/E, 50V, 0,35A, PQ=1,5W(1GHz)	55r	Mit	BFT99, 2SC2956
2SC1532	Si-N	S-L, 300/200V, 30A, 200W, >5MHz	88a	Tos	2SC1299, 2SC1302, 2SC1873, 2SD643, ++
2SC1533	Si-N	UHF-Tr/E, 45V, 0,5A, PQ=2,2W(700MHz)	55r	Fui	2SC1082
2SC1534	Si-N	UHF-Tr/E, 45V, 1A, PQ=7W(700MHz)	55r	Fui	—
2SC1535	Si-N	UHF-L, 45V, 2A, PQ=12W(700MHz)	55r	Fui	2SC1087
2SC1536	Si-N	UHF-L, 45V, 4A, PQ=24W(700MHz)	55r	Fui	—
2SC1537	Si-N	Uni, 50V, 0,03A, 0,15W, 200MHz	9c	Rhm	BC187, BC182, BC237, BC547, ++
2SC1538	Si-N	=2SC1537: ra	9c		BC184, BC414, BC550, 2SC1775(A), ++
2SC1538	Si-N	Uni, 25V, 0,03A, 0,15W, 200MHz	9c	Rhm	BC168, BC183, BC238, BC548, ++
2SC154(A..C,H)	Si-N	Vid, 120..200V, 0,1A, 0,75W, 150MHz	2a	Hit	BF258..259, BF656..659, 2N5056..59
2SC1540	Si-N	=2SC1539: ra	9c		BC169, BC184, BC239, BC549, ++
2SC1541	Si-N	Uni, 40V, 0,15A, 0,3W, 250MHz	9c	Rhm	BC167, BC182, BC237, BC547, ++
2SC1542	Si-N	=2SC1541: 25V	9c		BC188, BC183, BC238, BC548, ++
2SC1543	Si-N	Uni, 40V, 0,02A, 0,15W, <200/300ns	9c	Rhm	BC167, BC182, BC237, BC547, ++
2SC1544	Si-N	=2SC1543: 25V	9c		BC168, BC183, BC238, BC548, ++
2SC1545(M)	Si-N-Darl	Uni, 40V, 0,3A, 0,3W, 250MHz, B=10000	7c(C)	Rhm	BC517, BC617, BC875, MPS-A25..29, ++
2SC1548	Si-N-Darl	=2SC1545: 25V	7c(C)		BC517, BC817, BC875, MPS-A13..14, ++
2SC1547	Si-N	UHF, 900MHz	5g	Mat	BF377..378, BF689, BF763, 2N2857, ++
2SC1548	Si-N	VHF/UHF-L, 50V, 5A, PQ=23W(260MHz)	55r	Tos	BLX95, 2N6105
2SC1549	Si-N	NF/Vid, 150V, 0,05A, 0,75W, 130MHz	2a*	Fui	BF297..299, BF422, BFR87..89, ++
2SC155	Si-N	Min, HF, 20V, 25mA, 200MHz, β=35	≈36b	Fui	BC122..123, BC148, (BF254..255, ++)
2SC1550	Si-N	Vid-L, 250V, 0,1A, 10W, 100MHz	14h	Mat	BF415, BF417, BF458..459, 2SC3417, ++
2SC1551	Si-N	UHF, ra, 20V, 0,03A, 0,2W, 8,5GHz	51r	Tos	BFQ57..58, BFQ74, 2SC3278
2SC1552	Si-N	UHF, ra, 20V, 0,03A, 0,25W, 4,5GHz	51r	Tos	BFQ71, BFQ85, BFR14, BFR91
2SC1553(A)	Si-N	UHF, ra, 20V, 0,03A, 0,175W, 4,5GHz	5g	Tos	BFQ22
2SC1554	Si-N	UHF-A/Tr, 30V, 0,12A, 0,6W, 4GHz	51r	Tos	BFG34, BFG96
2SC1555	Si-N	=2SC1554: 1,2W	55r		BFQ34
2SC1556	Si-N	UHF-Tr/E, 30V, 0,12W, PQ>0,13W(500MHz)	5g	Tos	BFR95
2SC1557	Si-N	UHF-Tr/E, 40V, 0,18W, PQ>1W(1GHz)	5g	Tos	—
2SC1558	Si-N	UHF-A, 15V, 0,08A, 0,25W, 7GHz	51r	Tos	2SC2876, 2SC3358, 2SC3803
2SC1559	Si-N	UHF-A, 15V, 0,08A, 0,4W, 7GHz	51r	Tos	2SC2878, 2SC3358, 2SC3603
2SC156	Si-N	=2SC155: β=50	≈36b	Fui	BC122..123, BC148, (BF254..255, ++)
2SC1560	Si-N	UHF, ra, 25V, 0,07A, 0,58W, 4,5GHz	51s	Nec	BFP96, BFR96, BFQ73, 2SC2844
2SC1561	Si-N	UHF-Tr/E, 55V, 0,5A, PQ=3W(700MHz)	55r	Fui	2N4430
2SC1562	Si-N	UHF-Tr/E, 55V, 1A, PQ=9W(700MHz)	55r	Fui	—
2SC1563	Si-N	UHF-Tr/E, 55V, 2A, PQ=15W(700MHz)	55r	Fui	—
2SC1564	Si-N	UHF-Tr/E, 55V, 4A, PQ=30W(700MHz)	55r	Fui	—
2SC1565	Si-N	NF/S-L, 150V, 0,25A, 10W, 150MHz	14h	Mat	BD524
2SC1568	Si-N	Vid-L, 250V, 0,1A, 4W, 100MHz	14h	Mat	BF415, BF417, BF453..459, 2SC3417, ++
2SC1567	Si-N	NF/S-L, 100V, 0,5A, 5W, 120MHz	14h	Mat	BD139, BD230, BD379, 2SD1177..1178
2SC1567A	Si-N	=2SC1567: 120V	14h		2SC2690(A), 2SD1382, 2SD1563
2SC1568	Si-N	NF/S-L, 18V, 1A, 4W, 150MHz	14h	Mat	BD135, BD226, BD375, 2SD1380, ++
2SC1569	Si-N	Chroma-E, 300V, 0,15A, 12,5W, 100MHz	17j	Tos	2SC1505..1507, 2SC1755..1757, 2SC1905
2SC157	Si-N	Uni, 20V, 0,02A, 0,125W, β=30	2a	Hit	BC168, BC183, BC238, BC548, 2SD767++
2SC1570	Si-N	Uni, ra, 55V, 0,1A, 0,2W, 100MHz	7c	Say	BC414, BC550, 2SC2240, 2SC2459, ++
2SC1571	Si-N	=2SC1570: 40V	7c		BC184, BC413..414, BC550, 2SC2240, ++
2SC1572	Si-N	HF, 90V, 0,05A, 0,15W, 100MHz	2a	Mit	BF422, BSS38, BSW32, BSX21, ++
2SC1573(NC)	Si-N	NF, Vid, 250V, 0,07A, 1W, 60MHz	7c(9mm)	Mat	BF422A, BF392..393, 2SC3468..69, ++
2SC1573A	Si-N	=2SC1573: 300V	7c(9mm)		BF420A, BF393, 2SC3468..69, 2SC4168
2SC1573B	Si-N	=2SC1573: 400V	7c(9mm)		BF487, 2SC2267, 2SC3118, 2SC3469, ++
2SC1574	Si-N	UHF, ra, 20V, 0,03A, 0,4W, 4,5GHz	5g	Tos	(BFQ63)
2SC1576	Si-N	S-L, 450/330V, 8A, 100W, 10MHz	23a	Tos	BUW24..26, BUX18C, BUX44, 2SC2625, ++
2SC1577	Si-N	S-L, 500/400V, 8A, 60W, 7MHz	23a	Sak	BUW25..28, BUW34..38, 2SC3048, ++
2SC1578	Si-N	=2SC1577: 600/500V	23a		BUW25..28, BUW35..38, 2SC3046, ++
2SC1579	Si-N	S-L, 500/400V, 15A, 150W, 5MHz	23a	Sak	BUW44..46, BUV25, BUX25, 2SD641, ++

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2SC158	Si-N	=2SC157: β=40	2a	Hit	BC168, BC183, BC238, BC548, 2SD767++
2SC1580	Si-N	=2SC1579: 600/500V	23a		BUW45..46, BUS13, BUX48, 2SD641,++
2SC1581	Si-N+Di	AM-L, 65V, 7A, PQ=50W(30MHz)	59	Tos	—
2SC1582	Si-N+Di	AM-L, 65V, 13A, PQ=100W(30MHz)	59		—
2SC1583	Si-N	Dual, ra, 50V, 0,1A, 0,4W, 150MHz	5-SIP	Mit	2SC2259
2SC1584	Si-N	NF/S-L, 150V, 15A, 150W, 10MHz	23a	Sak	MJ15015, 2N3773, 2SC2607..08, 2SC3264++
2SC1585	Si-N	=2SC1584: 200V	23a		MJ15015, 2SC2607..08, 2SC3264, 2SD753++
2SC1586	Si-N	=2SC1584: 250V	23a		2SC3264, 2SD583
2SC1587	Si-N	UHF-L, 45V, 3A, PQ=30W(295MHz)	55r	Mit	BLX95, 2N6105
2SC1586	Si-N	VHF-Tr/E, 36V, 0,3A, PQ=0,4W(225MHz)		Nec	2SC1199, 2SC1252, 2SC1365, 2SC1368, ++
2SC1589	Si-N	VHF-Tr/E, 36V, 0,7A, PQ=1,5W(225MHz)	13m	Nec	—
2SC159	Si-N	=2SC157: β=50	2a	Hit	BC186, BC183, BC238, BC548, 2SD767++
2SC1590	Si-N	VHF-L, 36V, 1,2A, PQ=7W(225MHz)	56q	Nsc	—
2SC1591	Si-N	VHF-L, 36V, 2,5A, PQ=15W(225MHz)	56q	Nec	—
2SC1592	Si-N	UHF-A/Tr, 30V, 0,1A, 3,5W, 2,7GHz	55s	Nec	BFQ34, BFR94, 2SC1255
2SC1593	Si-N	UHF-A/Tr, 40V, 0,15A, 4,4W, 2GHz	55s	Nec	BFQ34, BFR94, 2SC1038, 2SC1041, ++
2SC1594	Si-N	UHF-A/Tr, 35V, 0,2A, 7W, 2,5GHz	55s	Nec	BFT98, 2SC1039, 2SC1042
2SC1595	Si-N	UHF-A/Tr, 35V, 0,3A, 7W, 2,5GHz	55s	Nec	BFQ86, 2SC1043, 2SC1250..1251
2SC1598	Si-N	Vid/S, 150V, 0,05A, 0,45W, 130MHz	2a	Fui	BF297..299, BF422, BFR87..89,++
2SC1597	Si-N	Vid/S, 150V, 0,05A, 0,45W, 130MHz	2a		BF297..299, BF422, BFR87..89,++
2SC1598	Si-N	UHF-Tr/E, 50V, 0,3A, 6W, >2000GHz	55s	Nec	BFQ68
2SC1599	Si-N	UHF-Tr/E, 50V, 0,3A, 6W, >2000GHz	62a	Nec	—
2BC16(A)	Si-N	Uni, 25V, 0,03A, 0,25W, >100MHz	2a	Tos	BC188, BC183, BC236, BC548, ++
2SC160	Si-N	=2SC157: β=80	2a	Hit	BC186, BC183, BC238, BC548, 2SD767++
2SC1600	Si-N	UHF-O/Tr, 40V, 0,25A, PQ=0,7W(1,7GHz)	2a	Nec	(2SC1253, 2SC1366)
2SC1601	Si-N	Uni, ra, 35V, 0,1A, 0,2W, 200MHz	≈2b	Njr	BC189, BC184, BC239, BC549, ++
2SC1602	Si-N	Uni, 35V, 0,1A, 0,15W, 200MHz	≈2b	Njr	BC168, BC183, BC238, BC548, ++
2SC1603	Si-N	UHF-Tr/E, 18V, 0,6A, PQ=1,5W(485MHz)	55r	Mit	BLW42, BLW79, BLX86, BLY38
2SC1604	Si-N	UHF-Tr/E, 18V, 0,3A, PQ=0,35W(485MHz)	51r	Mit	BLU98, MRF828, 2N6256, 2SC3019
2SC1805(A)	Si-N	VHF-L, 35V, 3,5A, PQ=18W(175MHz)	65r	Mit	BLY89, MRF209, 2N5591, 2N6082
2SC1606	Si-N	VHF-Tr/E, 40V, 0,6A, PQ=3W(175MHz)	51r	Mit	BLW17, 2SC1011, 2SC1405
2SC1607	Si-N	VHF/UHF, 40V, 0,1A, 0,18W	5g	Fui	BFX59
2SC1608	Si-N	UHF-Tr/E, 40V, 0,5A, PQ=1,6W(470MHz)	51r	Fui	BLX86
2SC1609	Si-N	S-L, 140V, 25A, 120W, <500/2000ns	23a	Nec	BUV10, BUW57, BUX10, BUX40,++
2SC161	Si-N	NF/S-L, 80V, 4A, 50W, 25MHz	23a	Tos	BD245A, BDV91, 2N4914..15, 2SD895,++
2SC1610	Si-N	S-L, 150V, 10A, 100W, <500/2000ns	23a	Nec	BD245D, BDX11, BUW70, 2N3442,++
2SC1613(A)	Si-N	Vid, 130V, 0,03A, 0,15W, 60MHz, A=ra	9c	Rhm	BF297..299, BF422, BFR87..89,++
2SC1814	Si-N	=2SC1613: 180V	9c	Rhm	BF298..299, BF422, BFR88..89,++
2SC1615	Si-N	=2SC1613: 210V	9c	Rhm	BF298..299, BF422, BFR88..89,++
2SC1617	Si-N	HV, TV-HA, S-L, 800/325V, 7A, 50W	23a	Tos	BU104, BU606..608, 2SD1154
2SC1818	Si-N	NF/S-L, 80V, 6A, 50W, 10MHz	23a	Sak	BD245B, BD313, BDX93, 2N5874,++
2SC1619	Si-N	=2SC1618: 100V	23a		BD245C, BDW21C, BDX95, 2N5832..34, ++
2SC1619A	Si-N	=2SC1819: 120V	23a		BD245C, BDX12, 2N4348, 2N5633..34, ++
2SC162	Si-N	VHF-A/Tr, 30V, 0,25A, 0,5W, 500MHz	2a	Oki	BFW16..17, BFX55, 2N3886
2SC1620	Si-N	UHF-Tr/E, 36V, 0,6A, PQ=2,6W(500MHz)	51r	Mat	BLX86
2SC1621	Si-N	SMD, S, 25V, 0,2A, <20/40ns	35a	Nec	BSV52, 2SC3578
2SC1822	Si-N	SMD, Uni, 40V, 0,1A, 110MHz	35a	Nec	BC846..847, BCW71..72, BCW81,++
2SC1622A	Si-N	=2SC1622: 120V	35a		2SC3324, 2SC4050
2SC1823	Si-N	SMD, Uni, 80V, 0,1A, 250MHz	35a	Nec	BC848, BCV71..72, 2SC3323
2SC1624	Si-N	NF/S-L, 120V, 1A, 15W, 30MHz	17j	Tos	BD239D, BD941, 2SC1669, 2SC2073, ++
2SC1625	Si-N	=2SC1624: 100V	17j		BD239C, BD939, 2SC1869, 2SC2073, ++
2SC1826	Si-N	=2SC1624: 80V, 0,75A	17j		BD239B, BD937, 2SC1669, 2SC2073, ++
2SC1627	Si-N	Uni, 80V, 0,3A, 0,8W, 100MHz	7c	Mic, Tos	BC639, 2N3700..01, 2SC4414, 2SD667, ++
2SC1627A	Si-N	=2SC1627: 0,4A, 0,8W	7c(9mm)		2SC2235, 2SC3939, 2SD667, 2SD1211, ++
2SC1828	Si-N	Vid, 180V, 0,05A, 120MHz	13m	Tos	BF460..462, MPS-U10, 2SC2224(A),++
2SC1829	Si-N	hi-beta, 90V, 6A, 50W, B>500	23a	Sak	2SC1831, 2SC2199, 2SD1831
2SC163	Si-N	=2SC162: 50V	2a	Oki	BFW16..17, BFX55, 2N3668
2SC1630	Si-N	Vid, 175V, 0,03A, 0,75W, 100MHz	2a	Son	BF258..259, BF658..659, 2N5058..58
2SC1831	Si-N	Uni, 25V, 0,2A, 0,25W, 140MHz	7c	Son	BC189, BC184, BC239, BC549, ++
2SC1632	Si-N	=2SC1831: 50V	7c		BC184, BC414, BC550, 2SC2240, ++
2SC1833	Si-N	Uni, 25V, 0,2A, 0,25W, 140MHz	7c	Son	BC186, BC183, BC236, BC548, ++
2SC1834	Si-N	=2SC1633: 50V	7c		BC167, BC162, BC237, BC547, ++
2SC1635	Si-N	S, 70V, 1A, 0,8W, <35/55ns	2a	Fui	BSS27, BSV95, 2N3735, 2SC1366
2SC1636	Si-N	hi-Ueb, hi-beta, ra, 50V, 0,02A, 30MHz	10b	Son	2SC3069, 2SC3615, 2SC3820, 2SD1915
2SC1637	Si-N	hi-Usb, 50V, 0,02A, 0,25W, 20MHz	10b	Son	2SC2878, 2SC3114, 2SC3135, (BC547,++)
2SC1836	Si-N	UHF-A/Tr, 40V, 0,3A, 0,6W, 1,4GHz	5g	Fui	2SC1199, 2SC1262, 2SC1365..1366

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2SC1639	Si-N	Uni, 25V, 0,03A, 0,25W, 200MHz	7c	Rhm	BC168, BC183, BC238, BC548, ++
2SC184	Si-N	=2SC162: 60V	2a	Oki	BFW18..17, BFX55, 2N3866
2SC1640	Si-N	Uni, ra, 25V, 0,03A, 0,25W, 200MHz	7c	Rhm	BC189, BC184, BC239, BC549, ++
2SC1641	Si-N	Uni, 40V, 0,15A, 0,3W, 250MHz	7c	Rhm	BC187, BC162, BC237, BC547, ++
2SC1642	Si-N	=2SC1641: 25V	7c		BC168, BC183, BC238, BC548, ++
2SC1643	Si-N	NF/S, 40V, 0,03A, 0,25W, <200/300ns	7c	Rhm	BC237, BC547, BSW41, BSY63, 2N708, ++
2SC1644	Si-N	=2SC1643: 25V	7c		BC238, BC548, BSY62..63, 2N706A, ++
2SC1645(S)	Si-N-Darl	=2SC1545:	7c,41c	Rhm	→2SC1545
2SC1648	Si-N-Darl	=2SC1546:	7c	Rhm	→2SC1548
2SC1647	Si-N	Uni, 50V, 0,03A, 0,25W, 200MHz	7c	Rhm	BC187, BC162, BC237, BC547, ++
2SC1646	Si-N	=2SC1647: ra	7c		BC414, BC550, 2SC2240, 2SC2459, ++
2SC1649	Si-N	=2SC1813: 0,25W	7c	Rhm	→2SC1613
2SC185	Si-N	=2SC162: 60V	2a	Oki	BFW16..17, BFX55, 2N3868
2SC1650	Si-N	=2SC1814: 0,25W	7c	Rhm	→2SC1814
2SC1651(S)	Si-N	=2SC1615: 0,25W	7c,41c	Rhm	→2SC1615
2SC1652(M)	Si-N	Uni, 40V, 0,5A, 0,3W, 250MHz	9c	Rhm	BC337, BC635, BC637, BC639, ++
2SC1653	Si-N	SMD, S, Nix, 150V, 0,05A, 120MHz	35a	Nec	BF622, BFN24, 2SC3143, 2SC3360, ++
2SC1654	Si-N	=2SC1653: 180V	35a		BF822, BFN24, 2SC3143, 2SC3360, ++
2SC1655(A)	Si-N	UHF, 16V, 0,03A, 0,15W, 8GHz	52s	Nec	BFG65, BFQ68, 2SC3267, 2SC3586..67
2SC1656	Si-N	UHF, 10V, 0,03A, 0,15W, 7GHz	52s	Nec	BFG65, BFQ66, 2SC3267, 2SC3566..87
2SC1657	Si-N	=2SC1655: Dual			—
2SC1656	Si-N	=2SC1656: Dual			—
2SC1659	Si-N	UHF, 20V, 0,06A, 0,5W, 7GHz	51s	Nec	2SC2676, 2SC3356, 2SC3803
2SC168	Si-N	HF/S, 30V, 0,03A, 0,2W	2a	Hit	BC168, BC183, BC238, BC548, ++
2SC1660	Si-N	UHF, 20V, 0,06A, 0,5W, 7GHz	51s	Nec	2SC2676, 2SC3356, 2SC3603
2SC1661	Si-N	=2SC1659: Dual			—
2SC1662	Si-N	=2SC1660: Dual			—
2SC1663	Si-N	S/Vid-L, 140V, 0,5A, 7,9W, 50MHz	13m	Son	BF460..462, MPS-U10, 2SC2224(A), ++
2SC1664	Si-N	hi-bata, 70V, 6A, 40W, B>500	22a	Sak	2SC2315..16, 2SC2491, 2SD1156
2SC1664A	Si-N	=2SC1654: 100V	22a		2SC2198, 2SC2491, 2SC2316
2SC1665	Si-N	UHF, 25V, 0,02A, 0,2W, 1,4GHz	5g	Nec	BF669, BFX62, BFX89, 2N2857
2SC1668	Si-N	VHF-Tr/E, 40V, 0,3A, 0,6W, 700MHz	5g	Nec	BFX55, 2SC1199, 2SC1252, 2SC1385..68
2SC1667	Si-N	NF/S-L, 90V, 4A, 50W(Tc=75°), 10MHz	23a	Mat	BD245C, BD313, BDX95, 2N5756..59, ++
2SC1666	Si-N	HF-L, 35V, 6A, 40W, 400MHz	55r	Tos	BLW20, BLW31, 2N6084
2SC1669	Si-N	NF/S-L, 150V, 1,5A, 25W, 6MHz	17j	Tos	2SC2073, 2SD576, 2SD608(A), 2SD1138
2SC167	Si-N	=2SC168: 55V	2a	Hit	BC167, BC182, BC237, BC547, ++
2SC1670	Si-N	Vid, 140V, 0,5A, 0,75W, 50MHz	7c(9mm)	Son	2SC2383, 2SC3228, 2SD1612
2SC1672	Si-N	S-L, 150V, 25A, 120W, <500/1000ns	23a	Nec	BD249D, BDW32, BUW39, BUW49, ++
2SC1673	Si-N	UHF-A/Tr, 35V, 0,3A, 7W, 2,5GHz	55s	Nec	BFQ68, BFT99
2SC1674	Si-N	FM-V/M/O, 30V, 20mA, 600MHz	7c	Nec	BF225, BF310, BF314, BF502, BF505++
2SC1675	Si-N	AM/FM-V/M/O, 50V, 30mA, 250MHz	7c	Nec	BF240..241, BF254..255, BF594..595, ++
2SC1676	Si-N	VHF-L, 50V, 3A, PQ>10W(270MHz)	55r	Tos	BLX95, 2N6105, 2SC2894
2SC1677	Si-N	VHF-L, 50V, 5A, PQ>19W(270MHz)	55r	Tos	—
2SC1678	Si-N	AM-L, 65V, 3A, PQ>3W(27MHz)	17j	Tos	2SC1306, 2SC1909, 2SC1964, 2SC2076, ++
2SC1679	Si-N	AM-L, 65V, 3A	17j	Tos	2SC1306, 2SC1909, 2SC1964, 2SC2076, ++
2SC166	Si-N	S, 20V, 0,2A, 0,25W, <50/60ns	2a	Oki	BSS11..12, BSY17..18, 2N2368..89(A), ++
2SC1660	Si-N	VHF-L, 35V, 2A, PQ=6W(175MHz)	55r	Tos	BLW19, BLW37, MRF212, 2N5590
2SC1661	Si-N	Uni, ra, 60V, 0,05A, 0,2W, 130MHz	7c	Tos	2SC1775(A), 2SC2089, 2SC2240, 2SC2390, ++
2SC1662	Si-N	=2SC1681: 40V	7c		BC164, BC414, BC550, 2SC2390, ++
2SC1683(A)	Si-N	NF/S-L, TV-VA, 200V, 0,5A, 30W, 6MHz	17j	Mat	BD239F, 2SC2238B, 2SC2660, 2SD1138
2SC1684(NC)	Si-N	Uni, 30V, 0,1A, 0,25W, 150MHz	7c	Mat, Mic	BC168, BC163, BC238, BC546, ++
2SC1665	Si-N	=2SC1664: 60V	7c		BC174, BC162, BC190, BC546, ++
2SC1668	Si-N	HF/ZF, 40V, 25mA, 0,25W, 330MHz	7d	Mat	BF198..199, BF224..225, BF596..597, ++
2SC1687	Si-N	HF/ZF, 40V, 30mA, 0,4W, 550MHz	7d	Mat, Mic	BF196..199, BF224..225, BF598..597, ++
2SC1668	Si-N	=2SC1687: 50V	7d		BF198..199, BF224..225, BF598..597, ++
2SC1689	Si-N	VHF-L, 55V, 3A, PQ=26W(220MHz)	55r	Mit	BLX95, 2N6105
2SC169	Si-N	=2SC168: 40V, <40/44ns	2a	Oki	BSS11, BSX19..20, 2N2368..69(A), ++
2SC1698	Si-N-Darl	S-L, 210V, 10A, 125W, B>1000	23a	Org	BUW26, BUW67, 2SD1027, 2SD1515, +
2SC17(A)	Si-N	Uni, 25V, 0,05A, 0,25W, 150MHz	2a	Tos	BC168, BC163, BC238, BC546, ++
2SC170	Si-N	HF, 25V, 0,05A, 0,11W, 250MHz	2a	Fui	BF240..241, BF254..255, BF594..595, ++
2SC1703	Si-N-Darl	S-L, 600V, 15A, 150W, B>100	23a	Org	BUT51, MJ10008..9, 2SD683, 2SD606, ++
2SC1708	Si-N	Vid, 200V, 0,05A, 0,2W, 60MHz	2a	Hit	BF296..299, BF422, BFR66..69, ++
2SC1707	Si-N	Uni, 40V, 0,1A, 0,2W, >100MHz	2a	Hit	BC167, BC183, BC238, BC548, ++
2SC1707A	Si-N	=2SC1707: 70V	2a		BC174, BC182, BC190, BC546, ++
2SC1708	Si-N	Uni, ra, 90V, 0,05A, 0,2W, 150MHz	7b	Mit	2SC1775(A), 2SC1645, 2SC2240, 2SC2459, ++
2SC1708A	Si-N	=2SC1706: 120V	7b		2SC1775A, 2SC1645, 2SC2240, 2SC2459, ++

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2SC1709	Si-N	S, 30V, 0,3A, 0,3W, -/125ns	7a	Fui	BSW41, BSX48, BSY63, 2N708, 2N914, ++
2SC171	Si-N	=2SC170: 0,2W	2a	Fui	BF240..241, BF254..255, BF594..595, ++
2SC1710	Si-N	UHF-Tr/E, 15V, 0,13A, 1W, 7GHz	≈55r	Fui	—
2SC1711(A)	Si-N	UHF, ra, 20V, 0,03A, 0,2W, 7,5GHz	52r	Fui	BFG65, BFQ66, 2SC1655..56, 2SC3276
2SC1712	Si-N	UHF, 16V, 0,03A, 0,2W, 6GHz	52r	Fui	BFG65, BFQ66, 2SC1655..56, 2SC3276
2SC1713	Si-N	=2SC1712: Dual			—
2SC1714	Si-N	=2SC1712: Dual			—
2SC1715	Si-N	=2SC1712: Dual			—
2SC1716	Si-N	=2SC1712: Dual			—
2SC1717	Si-N	VHF-L, 40V, 1A, PQ=2,2W(220MHz)	43a	Tos	—
2SC1718	Si-N	VHF-L, 35V, 4,5A, PQ=14W(220MHz)	55r	Tos	MRF209
2SC1719	Si-N	Vid, 150/120V, 0,05A, 1W, 130MHz	2a°	Fui	BF257..259, BF657..659, 2N5058..59
2SC172(A)	Si-N	HF, 25(A=40)V, 0,05A, 0,3W, 350MHz	2a	Fui	BF196..199, BF224..25, BF505, ++
2SC1720	Si-N	=2SC1719: 150/150V	2a°		BF257..259, BF657..659, 2N5059..59
2SC1721	Si-N	Uni, 80V, 1A, 0,5W, >100MHz	7c	Fui	BC639, 2SD667, 2SD1226, 2SD1766, ++
2SC1722	Si-N	Vid-L, 300V, 0,2A, 12,5W, 80MHz	17j	Hit	2SC1505..1507, 2SC1755..1757, 2SC1905
2SC1723	Si-N	=2SC1722: 15W, 60MHz	17j		2SC1505..1507, 2SC1755..1757, 2SC1905
2SC1724	Si-N	UHF-Tr/E, 35V, 0,8A, PQ=4W(470MHz)	55r	Tos	BLW43, BLW60, 2N5945
2SC1725	Si-N	UHF-L, 35V, 1,4A, PQ=7W(470MHz)	55r	Tos	BLU97, BLW14, BLX66, BLY53
2SC1726	Si-N	UHF-L, 35V, 2,8A, PQ=13W(470MHz)	55r	Tos	BLW15, BLX69, 2SC1338, 2SC1404
2SC1727	Si-N	VHF, ra, re, 700MHz	7f	Son	BF314, BF502, BF505, BF507, BF959++
2SC1726	Si-N	NF/S-L, 100V, 1A, 7,9W, 80MHz	13m	Son	BD419, BD529, 2SC2384
2SC1729	Si-N	VHF-L, 35, 3,5A, PQ=16W(175MHz)	56s	Mit	—
2SC173	Ge-N	HF, 15V, 5mA, 0,03W, 20MHz	≈2e	Son	—
2SC1730	Si-N	VHF/UHF, 1100MHz	7c	Nec	BF377..376, BF669, BF763, 2N2657, ++
2SC1731	Si-N	Dual, UHF, 20V, 0,05A, 3GHz		Nec	—
2SC1732	Si-N	Dual, UHF, 20V, 0,05A, 3GHz		Nec	—
2SC1733	Si-N	Dual, UHF, 30V, 0,05A, 2GHz	TO-71/6 Pin	Nec	—
2SC1734	Si-N	Uni, ra, 40V, 0,03A, 0,1W, 300MHz	2a	Hil	BC164, BC414, BC550, 2SC2390
2SC1735	Si-N	Uni, 100V, 0,5A, 0,8W, 130MHz	7b	Mit	BC639, 2SC3665, 2SD667(A), 2SD1618A ++
2SC1736	Si-N	Uni, 50V, 0,1A, 0,3W, 300MHz	7a	Mit	BC167, BC182, BC237, BC547, ++
2SC1737	Si-N	=2SC1736: 35V	7a		BC168, BC183, BC238, BC548, ++
2SC1736	Si-N	=2SC1636: ra, 35V	7a		BC169, BC164, BC239, BC549, ++
2SC1739	Si-N	Uni, 20V, 32mA, 0,25W, 300MHz	7c	Rhm	BC166, BC163, BC238, BC546, ++
2SC174	Si-N	HF, 30V, 25mA, 0,2W, 170MHz	5g	Fui	BF240..241, BF254..255, BF594..595, ++
2SC1740(S)	Si-N	Uni, 50V, 0,1A, 0,3W, 160MHz	7c, 41c	Rhm	BC167, BC182, BC237, BC547, ++
2SC1740LN	Si-N	=2SC1740: ra	7c		BC184, BC414, BC550, 2SC2675, ++
2SC1741(S)	Si-N	=2SC1652:	7c, 41c	Rhm	→2SC1652
2SC1741A	Si-N	=2SC1652: 50V, 0,4W	7c		→2SC1652
2SC1742	Si-N	UHF, ra, 20V, 0,03A, 0,15W, 6,5GHz	51r	Tos	BFQ57..56, BFQ74, 2SC1655..1656, ++
2SC1743	Si-N	UHF, ra, 20V, 0,03A, 0,175W, 4,5GHz	51r	Tos	BFQ71, BFT75, 2SC1119, 2SC1336, ++
2SC1744	Si-N	VHF-L, 35V, 10A, PQ=44W(175MHz)	60c	Tos	—
2SC1745	Si-N	Uni, ra, 60V, 0,05A, 0,15W, 140MHz	2a	Tos	2SC1775(A), 2SC2088..2089, 2SC2240, ++
2SC1746(A)	Si-N	=2SC1745: 50V	2a		BC414, BC550, 2SC2086..89, 2SC2240, ++
2SC1747	Si-N	UHF-A/Tr, 40V, 0,1A, 0,3W, >1400MHz	5g	Hit	BFX59
2SC1748	Si-N	S/Vid, 300V, 0,1A, 0,8W, 50MHz	2a	Nec	BF259, BF659, BFR59, BFS69, 2N5056
2SC1749	Si-N	Vid-L, 300V, 0,1A, 10W, 90MHz	17j	Mit	2SC1505..1507, 2SC1755..1757, 2SC1905
2SC174A	Si-N	=2SC174: 60V	5g		(BF240..241, BF254..255, BF594..595, ++)
2SC175	Ge-N	HF/ZF, 15V, 5mA, 0,03W, 10MHz	≈2e	Son	—
2SC1752	Si-N	MPS-A42	7e	Mot	→MPS-A42
2SC1753	Si-N	MPS-A43	7e	Mot	→MPS-A43
2SC1754	Si-N	=2N6426	7e	Mot	→2N6426
2SC1755	Si-N	NF/Vid-E-L, 300V, 0,2A, >50MHz	17j	Say	2SC1505..1507, 2SC1905
2SC1756	Si-N	=2SC1755	17j		2SC1505..1507, 2SC1905
2SC1757	Si-N	=2SC1755	17j		2SC1505..1507, 2SC1905
2SC1756	Si-N	Vid-L, 300V, 0,1A, 10W, 60MHz	13m	Nec	BF382, MPS-U10, (BF617, BF659, ++)
2SC176	Ge-N	HF/ZF, 15V, 5mA, 0,03W, 10MHz	≈2a	Son	—
2SC1760	Si-N	NF/S-L, 100V, 1A, 7,9W, 60MHz	13j	Son	2SC2275(A), 2SC2463, (BD419, BD529, ++)
2SC1761	Si-N	NF/S-L, 20V, 2A, 60MHz	13j	Son	2SC1173, 2SC1226, 2SC1386, 2SC1846, ++
2SC1782-1	Si-N	S, 700/400V, 0,3A, 0,47W, 13MHz	2a	Son	2N5012..5015, 2SD594
2SC1782-2	Si-N	=2SC1762-1: 800/450V	2a		2N5012..5015, 2SD594
2SC1763	Si-N	AM-L, 65V, 7A, PEP=40W(30MHz)	59r	Tos	—
2SC1764	Si-N	AM-L, 65V, 12A, PEP=60W(28MHz)	59r	Tos	MRF463..484
2SC1765	Si-N	UHF-Tr/E, 35V, 0,8A, PQ=3,2W(470MHz)	43a	Tos	—
2SC1766	Si-N	Uni, 30V, 0,1A, 0,31W, 230MHz	7a	Hit	BC168, BC163, BC238, BC546, ++
2SC1766	Si-N	hi-beta, 200V, 5A, 50W, B>400	23a		2SC1829, 2SD1090

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2SC1769	Si-N	Uni, 30V, 0,05A, 0,2W, 200MHz	7e	Njr	BC168, BC183, BC238, BC548, ++
2SC177	Ge-N	HF/ZF, 15V, 5mA, 0,03W, 10MHz	≈2e	Son	—
2SC1770	Si-N	Uni, 30V, 0,2A, 0,3W, 100MHz	7e	Njr	BC168, BC183, BC238, BC548, ++
2SC1771	Si-N	Uni, 60V, 0,2A, 0,3W, 100MHz	7e	Njr	BC174, BC182, BC190, BC546, ++
2SC1772	Si-N	Uni, 95V, 0,05A, 0,3W, 40MHz	7e	Njr	2SC1890(A), 2SC2240, 2SC2363, 2SD755, ++
2SC1773	Si-N	Uni, 30V, 0,4A, 0,5W, 100MHz	7e	Njr	BC337..338, BC835, BC637, BC639, ++
2SC1774	Si-N	=2SC1773: 60V	7e		BC337A, BC637, BC639, 2SD667, ++
2SC1775	Si-N	Uni, ra, 90V, 0,05A, 0,3W, 200MHz	7c	Hit	2SC2088..69, 2SC2240, 2SC2382, 2SC2389++
2SC1775A	Si-N	=2BC1775: 120V	7c		2SC2088, 2SC2240, 2SC2362, 2SC2389, ++
2SC1778	Si-N	Uni, 60V, 0,25A, 0,3W, 220MHz	7e	Ful	BC174, BC182, BC190, BC546, ++
2SC1777	Si-N	NF/S-L, 70V, 6A, 50W, 10MHz	23a	Sak	BD245A, BDV93, BDX93, 2N5874, ++
2SC1778	Si-N	VHF/UHF, 650MHz	7d	Mat, Mic	BF377..378, BF689, BF763, 2N2857, ++
2SC1779(A,B)	Si-N	VHF/UHF, re, 675MHz	7d	Mal	BF377..378, BF689, BF763, 2N2857, ++
2SC178	Ge-N	HF/ZF, 15V, 5mA, 0,03W, 20MHz	≈2e	Son	—
2SC1760	Si-N	UHF, ra, 25V, 15mA, 0,15W, 3GHz	9c	Mat	BFR15, BFS55, BFT68..67, BFW99
2SC1781	Si-N	Uni, 70V, 0,5A, 0,35W, 150MHz	2a	Hit	BC639, 2N2221..22(A), 2SD1225..26, ++
2SC1782	Si-N	NF/S-L, 140V, 10A, 100W, 10MHz	23a	Sak	BD245D, BDX11, 2N3442, 2SC2706, ++
2SC1783	Si-N	=2SC1782: 160V	23a		BD245E, BDW14, 2SC3283, 2SD555, ++
2SC1784	Si-N	S-L, 150V, 15A, 100W	23a	Sak	BDW12, BUX41, 2SD552, 2SD1047, ++
2SC1785	Si-N	=2SC1784: 200V	23a		BDW18, BUX41, 2SC3263..64, 2SD552, ++
2SC1788	Si-N	=2SC1784: 230V	23a		BUX41, 2BC1586, 2SC3263..64, 2SD563, ++
2SC1787	Si-N	Uni, ra, 35V, 0,03A, 0,15W, 150MHz	9c	Mat	BC169, BC164, BC238, BC549, ++
2SC1788(A)	Si-N	Uni, 25V, 0,5A, 0,6W, 150MHz	7c	Mat, Mic	BC337..338, BC635, BC637, BC839, ++
2SC1769	Si-N	VHF/ZF, 25V, 50mA, 0,4W, >600MHz	7c	Mat, Mic	BF377..378, BF689, BF763, 2N2857, ++
2SC179	Ge-N	S, 25V, 0,4A, 0, 12W, 3MHz	2a	Hit	ASY73..75
2SC1790	Si-N	UHF, 25V, 15mA, 0,15W, 3GHz	5g	Mat	BFR15, BFS55, BFT68..67, BFW99
2SC1791	Si-N	UHF-Tr/E, 45V, 1A, PQ=6W(1GHz)	55s	Nec	—
2SC1792	Si-N	UHF-L, 45V, 2A, PQ=10W(1GHz)	55s	Nec	—
2SC1793	Si-N	VHF-L, 45V, 4A, 42W, >300MHz	55s	Nec	BLW75, MRF314A, 2N5642
2SC1797	Si-N	UHF-Tr/E, 50V, 0,3APQ=1,6W(2GHz)	82a	Nec	—
2SC1798	Si-N	UHF-Tr/E, 50V, 1A, PQ=3,1W(2GHz)	62a	Nec	—
2SC1799	Si-N	UHF-L, 50V, 2A, PQ=6,3W(2GHz)	62e	Nec	—
2SC18	Si-N	Uni, 25V, 0,03A, 0,25W	2a	Tos	BC168, BC163, BC238, BC546, ++
2SC160	Ge-N	=2SC179: 5MHz	2a	Hit	ASY73..75
2SC1800	Si-N	UHF-L, 50V, 3A, PQ>10W(2GHz)	82e	Nec	—
2SC1601	Si-N	UHF, 1300MHz	7e	Njr	BF377..378, BF689, BF783, 2N2857, ++
2SC1802	Si-N	VHF/UHF, 700MHz	7e	Njr	BF377..378, BF689, BF783, 2N2857, ++
2SC1803	Si-N	UHF-ATr, 30V, 0,13A, 0,58W, 2,7GHz	51s	Nec	BFG34
2SC1804	Si-N	UHF-L, 47V, 1A, PQ=4,5W(770MHz)	55r	Mit	—
2SC1805	Si-N	UHF-L, 45V, 2A, PQ=12W(700MHz)	55r	Mit	—
2SC1806	Si-N	UHF-L, 45V, 4A, PQ=28W(700MHz)	55r	Mit	—
2SC1607	Si-N	UHF-O, 18V, 0,1A, PQ=25mW(485MHz)	5g	Mit	BFX59
2SC1608	Si-N	UHF-Tr/E, 35V, 1A, PQ=3,5W(485MHz)	55r	Mit	BLW43, BLW80
2SC1609(S)	Si-N	FM, 25V, 20mA, 500MHz	7c, 41c	Rhm	BF225, BF310, BF314, BF502, BF505++
2SC181	Ge-N	=2SC179: 10MHz	2a	Hit	ASY73..75
2SC1810	Si-N	TV-HA/SN, 700/300V, 0,3A, 7,9W	13c	Son	2SC3184, 2SD1527
2SC1811(-1,-2)	Si-N	Vid, 240V, 0,1A, 0,75W, 140MHz	7c(9mm)	Son	BF298..299, BF422(A), 2SC3468, ++
2SC1812	Si-N	UHF, re, 100MHz	25p	Son	2SC2144, 2SC2353, 2SC2464, 2SC2466, ++
2SC1813	Si-N	Uni, 50V, 0,5A, 0,5W, 100MHz	7e	Son	BC337, BC635, BC837, BC639, ++
2SC1815	Si-N	Uni, 60V, 0,15A, 0,4W, >80MHz	7c	Tos	BC174, BC182, BC190, BC548, ++
2SC1815L	Si-N	=2SC1815: ra	7c		BC550, 2SC2240, 2SC2874..75, 2SC3378
2SC1816	Si-N	AM-L, S-L, 100V, 4A, PQ=6W(27MHz)	17j	Son	2SC1306, 2SC1909, 2SC2043, 2SC2092
2SC1816H	Si-N	=2SC1818: hi-rel, 200V	17j		—
2SC1817	Si-N	AM-L, 45V, 5A, PQ=21W(27MHz)	17j	Son	—
2SC1818	Si-N	NF/S-L, 130V, 7A, 100W, 7MHz	23a	Mat	2SC2260..2262, 2SD551, 2SD731..732, ++
2SC1819	Si-N	Vid-L, 300V, 0,1A, 15W, 100MHz	17j	Mat	2SC1505..1507, 2SC1755..1757, 2SC1905
2SC182	Si-N	NF-E, 25V, 0,15A, 0,15W, 90MHz	24b	Nec	BC168, BC163, BC238, BC546, 2SD767++
2SC1820	Si-N	VHF-Tr/E, 55V, 0,5A, PQ=1,6W(175MHz)	2a	Ful	BFS23, BFW47, BLY34, 2N3553, 2N5160
2SC1821	Si-N	UHF-Tr/E, 55V, 0,5A, PQ=4W(470MHz)	55r	Ful	BLW90, 2SC2892
2SC1822	Si-N	UHF-L, 55V, 1A, PQ=7,5W(470MHz)	55r	Ful	BLX93, 2SC1040, 2SC2700
2SC1823	Si-N	UHF-L, 55V, 2A, PQ=15W(470MHz)	55r	Ful	BLW94, BLX94, MRF323, 2SC1118
2SC1824	Si-N	UHF-L, 55V, 4A, PQ=30W(470MHz)	55r	Ful	BLX95, 2N8105
2SC1825	Si-N	UHF-L, 55V, 8A, PQ=55W(470MHz)	≈57s	Ful	2N6439, 2SC2796
2SC1828	Si-N	NF/S-L, 60V, 4A, 30W, 10MHz	17j	Sak	BD243B, BD537, BD538B, BD951, ++
2SC1827	Si-N	=2SC1826: 100V	17j		BD243C, BD539C, BD953, 2SD712, ++
2SC1828	Si-N	S-L, 800V, 1A, 40W, 7MHz	22a	Sak	BUV38, BUX64..85, 2SC3149, 2SC3352

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2SC1829	Si-N	hi-beta, 200V, 5A, 100W, B>400	23a	Sak	2SD1090
2SC183(A)	Si-N	HF/ZF, 20(A=30)V, 0,03A, 0,1W, 150MHz	24b	Nec	BF240..241, BF254..255, BF594..595,++
2SC1830	Si-N-Darl	140V, 15A, 150W, B>500	23a	Sak	2SD710
2SC1831	Si-N	hi-beta, 90V, 8A, 100W, B>500	23a	Sak	2SD1831
2SC1832	Si-N-Darl	S-L, 500V, 15A, 150W, B>100	23a	Sak	BU932, 2SD711(A), 2SD572..573, 2SD683
2SC1833	Si-N	Uni, 60V, 0,2A, 0,3W, 300MHz	7c	Nec	BC182, BC548, BSV59, 2N2221..22(A),++
2SC1834	Si-N	S, 60V, 0,2A, 0,3W, <20/40ns	7c	Nec	—
2SC1835	Si-N	HF-L, 25V, 1A, 8W, 500MHz		Mit	—
2SC1836	Si-N	VHF-L, 25V, 5A, 30W, 500MHz	55r	Mit	BLW20, BLW31, 2N6084
2SC1837	Si-N	UHF-Tr/E, 35V, 0,6A, PO=1W(2GHz)	62d	Fui	—
2SC1838	Si-N	UHF-Tr/E, 35V, 1,5A, PO=3W(2GHz)	62d	Fui	—
2SC184	Si-N	AM-V/M, 20V, 0,03A, 0,1W, 200MHz	24b	Nec	BF240..241, BF254..255, BF594..595,++
2SC1840	Si-N	Uni, 40V, 0,1A, 0,5W, 100MHz	7c	Nec	BC167, BC182, BC237, BC547,++
2SC1841	Si-N	Uni, 120V, 0,05A, 0,5W, 110MHz	7c	Nec	2SC1890A, 2SC2363, 2SC2240, 2SC2459,++
2SC1842	Si-N	Uni, ra, 40V, 0,1A, 0,25W, 250MHz	7c	Nec	BC184, BC413..414, BC550, 2SC2240,++
2SC1843	Si-N	=2SC1842: 60V, 100MHz	7c	Nec	BC414, BC550, 2SC2240, 2SC2459,++
2SC1844	Si-N	Uni, ra, 60V, 0,1A, 0,5W, 100MHz	7c	Nec	BC414, BC550, 2SC2240, 2SC2459,++
2SC1845	Si-N	Uni, ra, 120V, 0,05A, 0,5W, 110MHz	7c	Nec	2SC1775A, 2SC1845, 2SC2240, 2SC2459,++
2SC1846	Si-N	NF/S-L, 45V, 1A, 5W, 200MHz	14h	Mat	BD135, BD226, BD375, 2SD1378,++
2SC1847	Si-N	NF/S-L, 50V, 1,5A, 5W, 150MHz	14h	Mat	BD137, BD228, BD377, 2SD794(A),++
2SC1848	Si-N	NF/S-L, 70V, 2A, 10W, 150MHz	13j	Mat	(2SC1398, 2SC2528, 2SC3252)
2SC1849	Si-N	Uni, 30V, 0,1A, 0,35W, 150MHz	7e	Mat, Mic	BC188, BC183, BC238, BC548,++
2SC185	Si-N	=2SC184: 250MHz	24b	Nec	BF240..241, BF254..255, BF594..595,++
2SC1850	Si-N	=2SC1849: 60V	7e		BC174, BC182, BC190, BC546,++
2SC1851	Si-N	Uni, 30V, 0,5A, 0,625W, 200MHz	7e	Mat, Mic	BC337..338, BC635, BC637, BC639,++
2SC1852	Si-N	=2SC1851: 60V	7e		BC337A, BC637, BC639, 2SD687,++
2SC1853	Si-N	HF-V/C4929M/O, 230MHz	7c	Mat	BF240..241, BF254..255, BF594..595,++
2SC1854	Si-N	Uni, 30V, 0,05A, 0,25W, 150MHz	7c	Mat	BC168, BC183, BC238, BC548,++
2SC1855	Si-N	TV-ZF, ra, 550MHz	7f	Hit	BF198, BF225, BF310, BF387, BF596++
2SC1856	Si-N	VHF, ra, 550MHz	7f	Hit	BF225, BF310, BF314, BF502, BF505++
2SC1857	Si-N	Vid, 300V, 0,1A, 0,8W, 60MHz	2a	Hit	BF259, BF859, BFR59, BFS89, 2N5058
2SC1859(-1,-2)	Si-N	Uni, 25V, 1,5A, 0,5W, 140MHz	17c	Son	2SC2238, 2SD773, 2SD787..788, 2SD1051
2SC186	Si-N	HF, 20V, 25mA, 0,085W, 200MHz, β=40	2a	Fui	BF240..241, BF254..255, BF594..595,++
2SC1860	Si-N	S, 150/100V, 2A, 12,5W(Tc=25°)	2a	Nec	BUX49..54, BUY41
2SC1861	Si-N	=2SC1860: 300/250V	2a		BUX52..54, BUY61..62
2SC1862	Si-N	=2SC1860: 450/400V	2a		BUX54, BUY61..62
2SC1863	Si-N	S-L, 150/100V, 7A, 40W, <1000/3000ns	22a	Nec	BUT56(A), BUX80..81, 2SC2200,++
2SC1864(A)	Si-N	=2SC1863: 300V	22a		BUT56(A), BUY85, 2SC2200, 2SC3039,++
2SC1865	Si-N	=2SC1863: 450/400V	22a	Nec	BUT41(A), BUY85, 2SC2200, 2SC3038,++
2SC1866	Si-N	S-L, 200/100V, 7A, 60W, <1000/3000ns	23a	Nec	BUX18(A..C), TIP55A..58A, 2SC3041,++
2SC1867(A)	Si-N	=2SC1866: 300V	23a		BUX18A..C, TIP55A..56A, 2SC3041,++
2SC1868	Si-N	=2SC1866: 450/400V	23a		BUX18C, TIP57A..58A, 2SC3041,++
2SC1869	Si-N	S-L, 200/100V, 10A, 100W, <1000/3000ns	23a	Nec	BUW24..26, BUX17(A..C), 2SC3520,++
2SC187	Si-N	=2SC186: β=50	2a	Fui	BF240..241, BF254..255, BF594..595,++
2SC1870	Si-N	=2SC1869: 300/250V	23a		BUW24..26, BUX17A..C, 2SC3520,++
2SC1871	Si-N	=2SC1869: 450/400V	23a		BUW24..26, BUX17C, 2SC3520,++
2SC1871A	Si-N	=2SC1869: 500/400V	23a		BUW24..26, BUX17C, 2SC3520,++
2SC1872	Si-N	S-L, 150/100V, 30A, 200W, <1000/3000ns	88a	Nec	2SC2128, 2SC2940, 2SC3224, 2SD540..541+
2SC1873	Si-N	=2SC1872: 300/250V	88a	Nec	2SC1299, 2SC1302, 2SC1401, 2SD643,++
2SC1874	Si-N	=2SC1872: 450/400V	88a		2SC1300, 2SC1470, 2SC2250, 2SD644,++
2SC1875	Si-N	CTV-HA, (90°), 1500/500V, 3,5A, 50W	23a	Nec	BU208..209, BU508(A), 2SD819, 2SD850++
2SC1878	Si-N-Darl	Uni, 100V, 0,5A, 0,8W, B>2000	2a	Hit	BSS52, 2SD406, 2SD688
2SC1879	Si-N-Darl+Di	Uni, 120V, 2A, 0,8W, B>1000	2a	Hit	2SD815
2SC188	Si-N	NF/HF/S, 40V, 0,5A, 0,6W, 150MHz	2a	Fui	BC140..141, BC300..302, 2N2218..19,++
2SC1880	Si-N-Darl+Di	=2SC1879: 15W	17c(A)		BDW53D, BDW63D, 2SD1147
2SC1881(K)	Si-N-Darl+Di	NF/S-L, 60V, 3A, 30W, B>1000	17c(A)	Hit	BD715, BDW23A, BDW53A, 2SD837,++
2SC1882	Si-N-Darl	S, 120V, 5A, 0,8W, B=5000	5	Hit	2SC2165
2SC1883	Si-N-Darl	NF/S-L, 120V, 5A, 30W, B>1000	17j	Hit	BD651, BDW63D, BDW73D, 2SD1147,++
2SC1884	Si-N-Darl	NF/S-L, 120V, 8A, 40W, B>1000	22a	Hit	BD651, BDT63C, BDW73D, BDX33D,++
2SC1885(NC)	Si-N	NF, ra, 150V, 0,05A, 0,75W, 200MHz	7c(9mm)	Mat	2SC2362K, 2SC2631..2632, 2SC3800
2SC1886	Si-N	UHF, 1000MHz	7c	Hit	BF377..378, BF689, BF763, 2N2857,++
2SC1887	Si-N	=2SC1886: 1100MHz	7c		BF377..378, BF689, BF763, 2N2857,++
2SC1888	Si-N	hi-beta, 60V, 3A, 0,8W, B=1000	2a	Sak, Tos	(2SC1963, 2SC3852, 2SD1157, 2SD1943,++)
2SC1889	Si-N	=2SC1888: 100V	2a		(2SC1984)
2SC189	Si-N	NF/HF/S, 60V, 0,5A, 0,6W, 150MHz	2a	Fui	BC140..141, BC300..302, 2N2218..19,++
2SC1890	Si-N	Uni, ra, 90V, 0,05A, 0,3W, 200MHz	7c	Hit	2SC2068..89, 2SC2240, 2SC2362, 2SC2389++

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2SC1890A	Si-N	=2SC1890: 120V	7c		2SC2088, 2SC2240, 2SC2362, 2SC2389, ++
2SC1891	Si-N	TV-HA, 1200/400V, 1,5A, 50W, 3MHz	23a	Tos	BU204..208, BU705, 2SC1922, 2SD818, ++
2SC1892	Si-N	TV-HA, 1500/500V, 2,5A, 50W, 3MHz	23a	Tos	BU205..208, BU705, 2SC1922, 2SD818, ++
2SC1893	Si-N	TV-HA, 1500/500V, 3,5A, 50W, 3MHz	23a	Tos	BU208..209, BU508(A), 2SD819, 2SD850++
2SC1894	Si-N	TV-HA, 1500/600V, 5A, 50W, 3MHz	23a	Tos	BU208(A), BU508(A), 2SC2928, 2SD820, ++
2SC1895	Si-N	TV-HA, 1500/600V, 6A, 50W, 2MHz	23a	Tos	BU508(A), BU908, 2SD649, 2SD821, ++
2SC1896	Si-N	TV-HA, 1500/600V, 7A, 50W, 2MHz	23a	Tos	BU508(A), BU908, 2SD822, 2SD1016, ++
2SC1897	Si-N	Uni, 30V, 1A, 0,6W, 200MHz	7c	Njr	BC337..337A, BC635, BC637, BC639, ++
2SC1898	Si-N	HF/ZF, 500MHz	7l	Njr	BF196..199, BF224..225, BF596..597, ++
2SC1899	Si-N	HF/ZF, 500MHz	7l	Njr	BF196..199, BF224..225, BF596..597, ++
2SC19	Si-N	NF/S, 40V, 0,4A, 0,6W, >70MHz	2a	Tos	BC140..141, BC300..302, 2N3053, ++
2SC190	Si-N	NF/HF/S, 60V, 0,5A, 0,6W, 180MHz	2a	Fui	BC140..141, BC300..302, 2N2218..19, ++
2SC1900	Si-N	Nix, 120V, 0,05A, 0,3W, 90MHz	7c	Njr	BF297..299, BSS38, 2SC2240, 2SD756, ++
2SC1901	Si-N	UHF, 25V, 0,02A, 0,6W, 1,4GHz	2a	Fui	(BFR37, BFW30, BFX73, BFX89, ++)
2SC1902	Si-N	VHF/UHF, 40V, 0,3A, 0,6W, 650MHz	2a	Fui	BFX55, 2SC1199, 2SC1252, 2SC1385..66
2SC1903	Si-N	Vid-L, 150/120V, 0,05A, 130MHz	14h	Fui	BF469, BF471, BF415, BF417, ++
2SC1904	Si-N	=2SC1903: 150/150V	14h		BF469, BF471, BF415, BF417, ++
2SC1905	Si-N	Vid-L, TV-HA, 350/300V, 0,2A, 15W	17j	Mat	(2SC1929, 2SC4714)
2SC1906	Si-N	VHF-M/O, 30V, 50mA, 1000MHz	7c	Hit	BF377..378, BF689, BF763, 2N2857, ++
2SC1907	Si-N	TV-Tuner, UHF-D, 30V, 50mA, 1100MHz	7c	Hit	BF377..378, BF689, BF763, 2N2857, ++
2SC1908	Si-N	VHF/S, 200MHz	7c	Son	BF240..241, BF254..255, BF594..595, ++
2SC1909	Si-N	AM-L, 75V, 3A, PQ=5,5W(27MHz)	17j	Nec	2SC1306, 2SC1816, 2SC2092
2SC191	Si-N	HF, 80V, 0,01A, 0,25W, 50MHz	2a	Son	(BF240..241, BF254..255, BF594..595, ++)
2SC1910	Si-N	Dual, UHF, 15V, 0,08A, 0,4W, 7GHz		Tos	—
2SC1911	Si-N	Dual, UHF, 20V, 0,03A, 0,3W, 8,5GHz		Tos	—
2SC1912	Si-N	Dual, UHF, 20V, 0,03A, 0,3W, 6,5GHz		Tos	—
2SC1913	Si-N	NF/S-L, 150V, 1A, 15W, 120MHz	17j	Mat	2SC2238(A), 2SC2344, 2SC2592, 2SD608(A)
2SC1913A	Si-N	=2SC1913: 180V	17j		2SC2238A, B, 2SC2344, 2SC2592, 2SD608A
2SC1914	Si-N	NF/Vid, 90V, 0,05A, 0,2W, 150MHz	7b	Mit	2SC1890(A), 2SC2240, 2SC2363, 2SD756, ++
2SC1914A	Si-N	=2SC1914: 120V	7b		2SC1890A, 2SC2240, 2SC2363, 2SD756(A), ++
2SC1915	Si-N	Vid, 120V, 0,05A, 0,8W, 200MHz	7b	Mit	BSS38, 2SC1890A, 2SC2240, 2SC2363, ++
2SC1916	Si-N	Uni, ra, 50V, 0,1A, 0,2W, 150MHz	7b	Mit	BC184, BC414, BC550, 2SC2240, ++
2SC1917	Si-N	=2SC1916: 35V	7b		BC169, BC184, BC239, BC549, ++
2SC1918	Si-N	Uni, 35V, 0,1A, 0,2W, 150MHz	7b	Mit	BC168, BC183, BC238, BC548, ++
2SC1919	Si-N	Uni, ra, 50V, 0,03A, 0,2W, 150MHz	7b	Mit	BC184, BC414, BC550, 2SC2240, ++
2SC192	Si-N	=2SC191: 10MHz	2a	Son	(BF240..241, BF254..255, BF594..595, ++)
2SC1920	Si-N	Dual, UHF, 15V, 0,08A, 0,4W, 7GHz		Tos	—
2SC1921	Si-N	Vid, 250V, 0,05A, 0,6W, 130MHz	7c(9mm)	Hit	BF296..299, BF422(A), 2SC3468, ++
2SC1922	Si-N	TV-HA, 1500/800V, 2,5A, 50W, 5MHz	23a	Hit	BU205..208, BU705, 2SD575, 2SD818, ++
2SC1923	Si-N	FM-V/M/ZF, 550MHz	7c	Tos, Mic	BF241, BF255, BF314, BF502, BF505++
2SC1924	Si-N	Dual, UHF, 20V, 0,05A, 3GHz		Nec	—
2SC1925	Si-N	Dual, UHF, 20V, 0,05A, 3GHz		Nec	—
2SC1926	Si-N	Dual, UHF, 30V, 0,05A, 2GHz		Nec	—
2SC1927	Si-N	Dual, UHF, 30V, 0,05A, 2GHz		Nec	—
2SC1928	Si-N	Uni, 50V, 0,05A, 0,315W, 140MHz	10b	Son	BC167, BC182, BC237, BC547, ++
2SC1929	Si-N	NF/S/Vid-L, 300V, 0,4A, 25W, 80MHz	17j	Mat	BUW40(A, B), 2SC1283(A), 2SC2022, ++
2SC193	Si-N	=2SC191: 30MHz	2a	Son	BF240..241, BF254..255, BF594..595, ++)
2SC1930(A)	Si-N	UHF, 16V, 0,03A, 0,15W, 8GHz	51r	Fui	2SC1655..56, 2SC3276, 2SC3586..87
2SC1931	Si-N	Dual, UHF, 16V, 0,03A, 0,3W, 8GHz		Fui	—
2SC1932	Si-N	Dual, UHF, 16V, 0,03A, 0,4W, 8GHz		Fui	—
2SC1933	Si-N	Dual, UHF, 15V, 0,04A, 0,4W, 6GHz		Fui	—
2SC1934	Si-N	Dual, UHF, 20V, 0,08A, 1W, 6GHz		Fui	—
2SC1935	Si-N	UHF, 15V, 0,03A, 0,25W, 6GHz	51r	Fui	BFQ57..58, BFQ74
2SC1936	Si-N	Dual, UHF, 15V, 0,03A, 0,3W, 6GHz		Fui	—
2SC1937	Si-N	UHF, 15V, 0,07A, 0,3W, 6GHz	51r	Fui	2SC2876
2SC1938	Si-N	Dual, UHF, 15V, 0,03A, 0,4W, 6GHz		Fui	—
2SC1939	Si-N	Dual, UHF, 15V, 0,03A, 0,4W, 6GHz		Fui	—
2SC194	Si-N	=2SC191	2a	Son	(BF240..241, BF254..255, BF594..595, ++)
2SC1940	Si-N	NF, 120V, 0,05A, 1W, 120MHz	9b	Nec	2SC2362..63, 2SC2631..32, 2SD2030, ++
2SC1941	Si-N	=2SC1940: 180V	9b		2SC2631..32, 2SC3248, 2SD2030
2SC1942	Si-N	TV-HA, 1500/600V, 3A, 50W, 5MHz	23a	Hit	BU208..209, BU705(A), 2SD819, 2SD850++
2SC1943	Si-N	UHF-Tr/E, 35V, 0,4A, PQ=0,4W(470MHz)	51r	Mit	BLU96, MRF627..828, 2N6256, 2SC3019
2SC1944	Si-N	AM-L, 80V, 6A, PQ=18W(27MHz)	17j	Mit	2SC1817, 2SC1969, 2SC2050, 2SC2098
2SC1945	Si-N	=2SC1944	17q		2SC3133
2SC1946	Si-N	VHF-L, 35V, 7A, PQ=32W(175MHz)	56s	Mit	—
2SC1946A	Si-N	=2SC1946: PQ=35W(175MHz)	56s		—

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2SC1947	Si-N	VHF-Tr/E, 35V, 1A, PQ=4W(175MHz)	2a(E=case)	Mit	BFS22, BFW46, MRF237, 2N3924
2SC1948	Si-N	UHF-A, 15V, 0,02A, 0,15W, 8GHz	52s	Nec	BFQ77, 2SC1655..56, 2SC1923, 2SC3276
2SC1949	Si-N	UHF-A, 30V, 0,13A, 0,58W, 2,7GHz	51s	Nec	BFG34
2SC195	Si-N	=2SC191: 30V, 10MHz	2a	Son	BF240..241, BF254..255, BF594..595,++
2SC1950	Si-N	UHF-Tr/E, 28V, 0,2A, 5W, 4GHz		Nec	2SC2093
2SC1951	Si-N	Vid, 120V, 0,1A, 0,75W, 140MHz	7c(9mm)	Son	BSS38, 2SC2240, 2SC2459, 2SC3245(A), ++
2SC1952	Si-N	UHF-A/Tr, 45V, 0,3A, 0,8W, 2GHz	2a	Nec	2SC1253, 2SC1366
2SC1953	Si-N	NF, 150V, 0,05A, 200MHz	14h	Mat	BF469, BF471, BF415, BF417,++
2SC1954	Si-N	UHF-A, re, 25V, 0,15A, 0,45W, 1,5GHz	7c	Fui	—
2SC1955	Si-N	VHF-Tr/E, 35V, 0,8A, PQ=3,2W(175MHz)	2a(E=case)	Tos	BFS22, BFW46, MRF237, 2N3924
2SC1956	Si-N	VHF-L, 35V, 3,5A, PQ=17W(175MHz)	55r	Tos	BLY69, MRF209, 2N5591, 2N5082
2SC1957	Si-N	AM-E, 75V, 1A, PQ=1,8W(27MHz)	14h	Nec	2SSC2091, 2SC2314
2SC1959	Si-N	Uni, 35V, 0,5A, 0,5W, 300MHz	7c	Tos	BC337..338, BC635, BC637, BC639,++
2SC196	Si-N	=2SC191 30V, 30MHz	2a	Son	BF240..241, BF254..255, BF594..595,++
2SC1960	Si-N	SS, 20V, 0,2A, 0,3W, -/15ns	7a	Fui	BSS11..12, BSY17..18, 2N2366..69(A),++
2SC1961	Si-N	FM, 35V, 25mA	7f	Son	BF240..241, BF254..255, BF594..595,++
2SC1962	Si-N	NF/S/Vid-E, 200V, 0,5A, 45MHz	13m	Son	BF381..382, BF460..482, MPS-U10
2SC1963	Si-N	Dual, 25V, 0,2A, 0,27W, 140MHz	6ᵃDIP	Son	—
2SC1964	Si-N	AM-L, 80V, 3,5A, PQ=3,4W(27MHz)	17j	Mil	2SC1678..79, 2SC2075, 2SC2078
2SC1965(A)	Si-N	VHF-L, 35..40V, 1..2A, PQ=6,5W(175MHz)	43a(E=case)	Mit	—
2SC1966	Si-N	UHF-L, 35V, 1A, PQ=3,5W(470MHz)	58s	Mll	2SC3020
2SC1967	Si-N	UHF-L, 35V, 2A, PQ=8W(470MHz)	58s	Mit	2SC2992, 2SC3021
2SC1968(A)	Si-N	UHF-L, 35V, 5A, PQ=16W(470MHz)	58s	Mit	2SC3022
2SC1969	Si-N	AM-L, 60V, 6A, PQ=16W(27MHz)	17j	Mit	2SC1944, 2SC2050, 2SC2098
2SC197	Si-N	=2SC191: 30V	2a	Son	BF240..241, BF254..255, BF594..595,++
2SC1970	Si-N	VHF-Tr/E, 40V, 0,6A, PQ=1,3W(175MHz)	17j	Mit	—
2SC1971	Si-N	VHF-L, 35V, 2A, PQ=7W(175MHz)	17q	Mit	—
2SC1972	Si-N	VHF-L, 35V, 3,5A, PQ=15W(175MHz)	17q	Mit	—
2SC1973	Si-N	HF-O/Tr, 50V, 0,5A, PQ=1W(50MHz)	7c(9mm)	Mat	(MRF229, 239)
2SC1974	Si-N	HF-L, 80V, 2A, PQ=5W(50MHz)	17j	Mat	—
2SC1975	Si-N	HF-L, 120V, 2A, PQ=3,8W(50MHz)	17j	Mat	—
2SC1976	Si-N	VHF-E, 36V, 0,5A(ss), PQ>0,6W(175MHz)	7c(9mm)	Mat	(BRF96, MRF207, MRF225, MRF807)
2SC1977	Si-N	VHF-L, 36V, 1A(ss), PQ>2W(175MHz)	14h	Mat	—
2SC1978	Si-N	VHF-L, 36V, 1,5A(ss), PQ>7W(175MHz)	17j	Mat	—
2SC198(A)	Si-N	VHF-A/Tr, 50V, 0,5A, 0,8W, 350MHz	5g	Fui	BFS23, BFX55, BLY34, 2SC2852
2SC1980	Si-N	Uni, ra, 120V, 0,02A, 0,25W, 200MHz	7c	Mat	2SC2088, 2SC2240, 2SC2362, 2SC2389
2SC1981	Si-N	hi-Ueb, hi-beta, 50V, 0,1A, 0,3W, 30MHz	2a	Son	2SC3069, 2SC3815, 2SC3820, 2SC3836
2SC1982	Si-N	NF/HF/S, 140V, 1A, 0,625W, 120MHz	2a	Son	BSS43, BSW68, 2N3019..20, 2SC1860
2SC1983	Si-N	hi-beta, 80V, 3A, 30W, B=700	17j	Sak	2SD1157, 2SD1943
2SC1984	Si-N	=2SC1983: 100V	17j		2SC2316, 2SC2491
2SC1985	Si-N	NF/S-L, 80V, 6A, 40W, 10MHz	17j	Sak	BD243B, BD543B, BD799, BD809,++
2SC1986	Si-N	=2SC1985: 100V	17j		BD243C, BD543C, BD601, 2SD613,++
2SC1987	Si-N	TV-HA, S-L, 300V, 6A, 50W, 12MHz	22a	Hit	BU406..406, 2SD884..885, 2SD1163,++
2SC1988	Si-N	UHF, ra, 25V, 0,07A, 0,35W, 4,5GHz	5g	Nec	BFQ63
2SC1989	Si-N	HF/ZF, 300MHz	7c	Mat	BF240..241, BF254..255, BF594..595,++
2SC199	Si-N	HF/S, 80V, 0,05A, 0,6W, 130MHz	2a	Tos	(BC140..141, BC300..301, BSW39)
2SC1990	Si-N	HF/ZF, 650MHz	7c	Mat	BF196..199, BF224..225, BF596..597,++
2SC1991	Si-N	Uni, 60V, 0,1A, 0,625W, 250MHz	7e	Nec	BC174, BC182, BC190, BC546,++
2SC1992	Si-N	Uni, 50V, 0,1A, 0,3W, 300MHz	7a	Nec	BC167, BC182, BC237, BC547,++
2SC1993	Si-N	Uni, 30V, 0,1A, 0,3W, 300MHz	7a	Nec	BC188, BC163, BC238, BC548,++
2SC1994	Si-N	Uni, ra, 45V, 0,1A, 0,3W, 300MHz	7a	Nec	BC184, BC413..414, BC550, 2SC2240,++
2SC1995	Si-N	=2SC1994: 50V	7a		BC414, BC550, 2SC2240, 2SC2390,++
2SC1996	Si-N	Uni, 50V, 0,6A, 0,825, 100MHz	7a	Nec	BC337, BC637, BC639, 2SD667,++
2SC1997	Si-N	=2SC1997: 30V	7a		BC337..338, BC635, BC637, BC639,++
2SC1998	Si-N	Uni, 80V, 0,1A, 0,5W, 300MHz	7a	Nec	BC548, 2SC2240, 2SC2459, 2SC3245(A),++
2SC1999	Si-N	=2SC1998: 50V	7a	Nec	BC167, BC182, BC237, BC547,++
2SC20	Si-N	NF/S, 40V, 0,4A, 0,6W, 90MHz	2a	Tos	BC140..141, BC300..302, 2N3053,++
2SC200	Si-N	VHF-A/Tr, 40V, 0,3A, 0,65W, 350MHz	2a	Fui	BFS23, BFX55, BLY34, 2SC2852
2SC2000	Si-N	Uni, 60V, 0,2A, 0,6W, 70MHz	7c	Nec	BC174, BC182, BC190, BC548,++
2SC2001	Si-N	Uni, 30V, 0,7A, 0,6W, 170MHz	7c	Nec	BC337..338, BC635, BC637, BC639,++
2SC2002	Si-N	Uni, 60V, 0,3A, 0,6W, 140MHz	7c	Nec	BC337A, BC637, 2SD667, 2SC3939,++
2SC2003	Si-N	=2SC2002: 80V	7c		BC839, 2SD687, 2SD1225, 2SD1788,++
2SC2008	Si-N	HF, 35V, 0,1A, 560MHz	7a	Son	BF370, BF920..921S, BF959
2SC2009	Si-N	VHF/ZF, 550MHz	7l	Son	BF370, BF920..921S, BF959,++
2SC201	Si-N	=2SC200: 20V	2a	Fui	BFS23, BFX55, BLY34, 2SC2852
2SC2010	Si-N	HF, 35V, 0,03A, 400MHz	7l	Son	BF196..199, BF224..225, BF596..597,++

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2SC2011	Si-N	VHF/ZF, 630MHz	7f	Son	BF198, BF225, BF310, BF314, BF505++
2SC2012	Si-N	HF, 30V, 0,03A, 0,5W, 200MHz	7c	Son	BF240..241, BF254..255, BF594..595,++
2SC2013	Si-N	VHF, ra, 700MHz	7f	Son	BF225, BF314, BF502, BF505, BF507++
2SC2014	Si-N	Uni, 100V, 0,2A, 0,5W, 100MHz	7c	Son	2SC2240, 2SC2459, 2SC2345(A), 2SC3248
2SC2017	Si-N	S-L, 450/400V, 10A, 100W, >10MHz	23a	Mit	BUW24..26, BUW72, BUX14, 2SC3520, ++
2SC2016	Si-N	S-L, 300/300V, 15A, 100W, >10MHz	23a	Mit	BUX13, BUY50, MJ15024, 2SC2307, ++
2SC2019	Si-N	S-L, 200/200V, 15A, 100W, >10MHz	23a	Mit	BUX41, 2SC2944, 2SD552, 2SD583, ++
2SC202	Si-N	=2SC200: 80V	2a	Fui	—
2SC2020	Si-N	AM-L, 45V, 2A, PQ=7W(27MHz)	17j	Son	2SC1816, 2SC2029, 2SC2043
2SC2021(M,LN)	Si-N	=2SC1740(LN):	9c	Rhm	→2SC1740(LN)
2SC2022	Si-N	S-L, 300/300V, 1A, 30W, 10MHz	17j	Sak	TIP47..50, 2SC2023, 2SD859(A,B), ++
2SC2023	Si-N	S-L, 300/300V, 2A, 40W, 10MHz	17j	Sak	TIP75(A..C), 2SC2738, 2SC3055, ++
2SC2024	Si-N	Relais-Tr, 80V, 1A, 150MHz	14h	Fui	BD139, BD230, BD379, 2SD1177..1178
2SC2025	Si-N	UHF, ra, 35V, 0,05A, 0,35W, 2,2GHz	5q	Nec	BFR37, BFS55, BFW30, BFX73,
2SC2026	Si-N	UHF, 30V, 0,05A, 0,25W, 2,2GHz	7f	Nec	BF357, 2SC2570(A), 2SC3037
2SC2027	Si-N	TV-HA, 1500/800V, 5A, 50W, 8MHz	23a	Hit	BU208(A), BU508(A), 2SC2928, 2SD820, ++
2SC2028	Si-N	AM-L, 80V, 1,5A, PQ=0,7W(27MHz)	14h	Fui	2SC1957, 2SC2091, 2SC2314
2SC2029	Si-N	AM-L, 80V, 2A, PQ=6W(27MHz)	17j	Fui	2SC1816, 2SC2020
2SC203	Si-N	HF/S, 40V, 0,2A, 0,35W, 350MHz	2a	Fui	BSW41, BSY63, 2N708, 2N914, 2N4123, ++
2SC2031	Si-N	UHF-Tr/E, 45V, 0,5A, PQ=2,5W(470MHz)	55r	Fui	BLW90, BLX92, 2SC2892
2SC2032	Si-N	UHF-L, 45V, 1A, PQ=5,5W(470MHz)	55r	Fui	BLW93, BLX93, 2SC1040, 2SC2700
2SC2033	Si-N	UHF-L, 45V, 3A, PQ=18W(470MHz)	55r	Fui	BLW94, BLX94, 2SC2894
2SC2034	Si-N	HF-Tr/E, 120V, 2A, PQ=3,8W(50MHz)	2a	Mat	—
2SC2035	Si-N	Uni, 50V, 0,3A, 0,3W, 350MHz	7a	Fui	(BC337, BC637, BC839, 2SD667, ++)
2SC2036	Si-N	AM-TR/E, 80V, 1A, PQ=1..4W	14h	Tos	—
2SC2037	Si-N	UHF, 30V, 0,05A, 0,25W, 2GHz	7a	Nec	BF357, 2SC2570(A), 2SC3037
2SC2039	Si-N	HF-L, 70V, 5A, 75W, 200MHz		Mit	—
2SC2039	Si-N	AM-L, 70V, 8A, PQ=50W(30MHz)	≈57s	Mit	—
2SC204(F)	Si-N	=2SC203: 30V, 250MHz	2a	Fui	BSW41, BSY63, 2N708, 2N914, 2N4123, ++
2SC2040	Si-N	VHF-Tr/E, 40V, 0,5A, 5W, 1,8GHz	55r	Mit	—
2SC2043	Si-N	AM-L, 70V, 4A, PQ=16W(27MHz)	17j	Fui	2SC1817, 2SC1944, 2SC1969, 2SC2098
2SC2044	Si-N	UHF-L, 55V, 6A, PQ=42W(770MHz)	≈57s	Fui	—
2SC205	Si-N	=2SC203: 80V	2a	Fui	BSW63..64, 2N2221A..2222A
2SC2050	Si-N	AM-L, 80V, 8A, PQ>13W(50MHz)	17j	Mat	2SC1307
2SC2051	Si-N	Uni, 80V, 0,25A, 0,5W, 300MHz	7c	Fui	BC337A, BC637, BC839, 2SD667, ++
2SC2053	Si-N	VHF-O/Tr, 40V, 0,3A, PQ=0,2W(175MHz)	7b	Mit	2SC2851
2SC2055	Si-N	VHF-Tr/E, 18V, 0,3A, PQ=0,25W(175MHz)	7b	Mit	2SC2851
2SC2056	Si-N	VHF-Tr/E, 18V, 0,6A, PQ=2W(175MHz)	2a(E=case)	Mit	BFQ42, BFS22, BLY33, MRF237, 2SC2852
2SC2057	Si-N	VHF/ZF, 500MHz	7d	Say	BF198, BF225, BF310, BF314, BF502++
2SC2058(S)	Si-N	HF, 40V, 0,05A, 0,25W, 300MHz	7c, 41c	Rhm	BF240..241, BF254..255, BF594..595, ++
2SC2059	Si-N	SMD, FM, 25V, 0,02A, 500MHz	≈35d	Rhm	—
2SC2059K	Si-N	=2SC2059:	35a		BF599, BF799, 2SC3015, 2SC3374
2SC206	Si-N	VHF, 20V, 25mA, 0,2W, 200MHz	5g	Fui	BF225, BF310, BF314, BF502, BF505++
2SC2060	Si-N	Uni, 40V, 1A, 0,75W, 150MHz	7c(9mm)	Rhm	2SD867, 2SD863, 2SD1331, 2SD1207, ++
2SC2061	Si-N	Uni, 80V, 0,7A, 0,75W, 120MHz	7c(9mm)	Rhm	2SC3228, 2SD667, 2SD1292, 2SD1812, ++
2SC2062(S)	Si-N-Darl	Uni, 40V, 0,3A, 0,3W, 200MHz, B>5000	5c	Rhm	BC517, BC617, BC875, MPS-A25..29, ++
2SC2063(M)	Si-N	=2SC2059:	9c	Rhm	→2SC2059
2SC2065	Si-N	UHF-Tr/E, 35V, 0,25A, 6W, 3,2GHz	55s	Nec	BFQ68
2SC2066	Si-N	UHF-Tr/E, 35V, 0,45A, 7W, 2GHz	55s	Nec	BFT99
2SC2067	Si-N	Uni, 35V, 1A, 0,5W, 150MHz	7c	Fui	BC337..338, BC635, BC637, BC639, ++
2SC2068	Si-N	CTV-Chroma-E, 300V, 0,05A, 95MHz	13j	Tos	(BF461..462, BF756..759, MPS-U10, ++)
2SC2069	Si-N	S, 20V, 0,3A, 0,35W, -/100ns	2a	Fui	BSW41, BSX87..88, BSY62..63, 2N706A++
2SC207	Si-N	=2SC206: 800MHz	5g	Fui	BF377..378, BF689, BF763, 2N2857, ++
2SC2070	Si-N	S, 40V, 0,3A, 0,3W, <160/172ns	2a	Fui	BSW41, BSX87..88, BSY63, 2N914, ++
2SC2071	Si-N	Vid, 250V, 0,05A, 130MHz	14h	Fui	BF469, BF471, BF415, BF417, ++
2SC2072	Opto			Son	—
2SC2073	Si-N	TV-VA, NF/S-L, 150V, 1,5A, 25W, 4MHz	17j	Tos	BD239D, 2SC1689, 2SD608(A), 2SD1139, ++
2SC2075	Si-N	AM-L, 80V, 4A, PQ>3,5W(27MHz)	17j	Tos	2SC1306, 2SC1816, 2SC1909, 2SC2092
2SC2076	Si-N	FM, 150MHz	7c	Mat	BF240..241, BF254..255, BF594..595, ++
2SC2078	Si-N	AM-L, 80V, 3A, PQ>4W(27MHz)	17j	Say	2SC1306, 2SC1818, 2SC1909, 2SC2092
2SC2079	Si-N	Uni, 100V, 0,7A, 1W, 100MHz	7c*	Say	BC639, BCX24, 2SC2235, 2SD667, ++
2SC208	Si-N	=2SC206: 550MHz	5g	Fui	BF377..378, BF689, BF763, 2N2857, ++
2SC2080	Si-N	NF/S-L, 80V, 1A, 35/105ns	14h	Fui	BD137, BD228, BD377, 2SD1378
2SC2081	Si-N	UHF-Tr/E, 36V, 0,75A, PQ>2,8W(500MHz)	55s	Nec	BLW43, BLW80, 2N5945
2SC2082	Si-N	UHF-L, 38V, 2,2A, PQ>7,9W(500MHz)	55s	Nec	BLW44, 2N5946
2SC2083	Si-N	UHF-L, 39V, 3A, PQ=14W(500MHz)	55s	Nec	BLW15, BLX69, 2SC1338

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2SC2085	Si-N	NF/S, Vid-L, 300V, 0,1A, 10W, 55MHz	17j	Mat	2SC1505..1507, 2SC1755..1757, 2SC1905
2SC2086	Si-N	AM-O/Tr, 75V, 1A, PQ=0,45W(27MHz)	7b	Mit	—
2SC2087	Si-N	Vid, 300V, 5mA, 0,1W, 80MHz	2a	Oki	BF299, BF420, BF483, BFR89, ++
2SC2088	Si-N	Uni, ra, 120V, 0,05A, 0,3W, 150MHz	7c	Tos	2SC1775A, 2SC1845, 2SC2240, 2SC2459, ++
2SC2089	Si-N	Uni, ra, 120V, 0,05A, 0,3W, 150MHz	7c	Tos	2SC1775A, 2SC1845, 2SC2240, 2SC2459, ++
2SC209	Si-N	=2SC206: 450MHz	5g	Fui	BF377..378, BF689, BF763, 2N2557, ++
2SC2091	Si-N	AM-L, 75V, 1A, PQ=1,8W(27MHz)	14h	Hit	2SC1957, 2SC2314
2SC2092	Si-N	AM-L, 75V, 3A, PQ=5W(27MHz)	17j	Hit	2SC1306, 2SC1818, 2SC1909,
2SC2093	Si-N	UHF-ATr/E, 28V, 0,2A, PQ=0,25W(5GHz)		Nec	2SC1950
2SC2094	Si-N	VHF/UHF-L, 40V, 3,5A, PQ>17,5W(175MHz)	58s	Mit	—
2SC2097	Si-N	AM-L, 50V, 15A, PQ=85W(30MHz)	≈57s	Mit	—
2SC2098	Si-N	AM-L, 70V, 6A, PQ=15W(28MHz)	17j	Tos	2SC1944, 2SC1989, 2SC2050, 2SC1817
2SC2099	Si-N	AM-L, 40V, 6A, PEP=20W(28MHz)	59r	Tos	—
2SC21	Si-N	NF/HF/S-L, 80V, 2A, 60W, 6MHz	23a	Tos	BD245A, BD311, BD313, 2N4914..15, ++
2SC210	Si-N	HF/S, 50V, 0,5A, 0,65W, 150MHz	2a	Fui	SC140..141, BC300..302, 2N3053, ++
2SC2100	Si-N	AM-L, 40V, 15A, PEP=60W(28MHz)	59r	Tos	MRF421, 2SC2290
2SC2101	Si-N	VHF-L, 35V, 2A, PQ>8W(175MHz)	55r	Tos	BLW19, MRF208, MRF212, 2N5590
2SC2102	Si-N	VHF-L, 35V, 3,5A, PQ>15W(175MHz)	55r	Tos	BLY89, MRF209, 2N5591, 2N6082
2SC2103(A)	Si-N	VHF-L, 40V, 6A, PQ>24W(175MHz)	55r	Tos	BLW20, BLW31, 2N6084
2SC2104	Si-N	UHF-Tr/E, 35V, 0,6A, PQ>3W(470MHz)	55r	Tos	2N5945
2SC2105	Si-N	UHF-L, 35V, 1,4A, PQ>8W(470MHz)	55r	Tos	BLW14, BLW44, 2N5946
2SC2106	Si-N	UHF-L, 35V, 2,8A, PQ>12W(470MHz)	55r	Tos	BLW15, BLX89, 2SC1338
2SC2107	Si-N	SMD, 80V, 0,1A, 300MHz	35a	Nec	BC848, BCV71..72, BSR17, 2SC3381
2SC2108	Si-N	HF/S, 120V, 0,7A, 0,8W, 250MHz	2a	Nec	2N2102, 2N2405, 2SC959
2SC2109	Si-N	Uni, 80V, 0,2A, 0,3W, 300MHz, 45/400ns	7a	Nec	BC174, BC182, BC546, 2N3903..04, ++
2SC211	Si-N	=2SC210: 25V	2a	Fui	BC140..141, BC300..302, 2N3053, ++
2SC2111	Si-N	S, 40V, 0,2A, 0,3W, 500MHz, <20/40ns	7a	Nec	BSS11, BSX19..20, 2N2368..69(A), ++
2SC2113	Si-N	NF/HF/S-L, 40V, 1A, 4W, 100MHz	14h	Mat	BD135, BD226, BD375, 2SC3419, ++
2SC2114	Si-N	UHF-A, 15V, 0,08A, 0,225W, 7GHz	24l	Tos	2SC2876, 2SC3062
2SC2115	Si-N	UHF-A, 20V, 0,03A, 0,15W, 6,5GHz	24l	Tos	BFQ57..58, BFQ74, 2SC1655..1659, ++
2SC2116	Si-N	UHF-A, 30V, 0,05A, 0,225W, 3GHz	24f	Tos	BFQ72, BFT65
2SC2117	Si-N	VHF-Tr/E, 35V, 0,8A, PQ=3,2W(175MHz)	43a(E=case)	Tos	—
2SC2118	Si-N	VHF-L, 35V, 1,4A, PQ=6W(175MHz)	43a(E=case)	Tos	—
2SC2119	Si-N	AM-L, 80V, 4A, PQ>8W(28MHz)	17j	Tos	2SC1818, 2SC2043
2SC212	Si-N	=2SC210: 80V	2a	Fui	BC140..141, BC300..301, 2N1990, ++
2SC2120	Si-N	Uni, 30V, 0,6A, 0,6W, 120MHz	7c	Tos, Mic	BC337..338, BC635, BC637, BC639, ++
2SC2121	Si-N	S-L, 750/300V, 3A, 50W, 8MHz	23a	Tos	BU128, BU328(A), BU426(A), 2SD1183
2SC2122	Si-N	TV-HA, 800/325V, 10A, 50W, 6MHz	23a	Tos	BU626A, 2SC2123, 2SD1094, 2SD1279
2SC2122A	Si-N	=2SC2122: 1000/400V	23a		BU626A, 2SC2123, 2SD1094, 2SD1279
2SC2123	Si-N	TV-HA, 1000/400V, 12A, 50W, 6MHz	23a		(BU626A, 2SD1094, 2SD1279)
2SC2124	Si-N	TV-HA, 2200/800V, 2A, 5W(Tc=90°)	23a	Tos	BU225, BUY71, 2SD621, 2SD838
2SC2125	Si-N	TV-HA, 2200/800V, 5A, 50W, 5MHz	23a	Tos	—
2SC2126(A)	Si-N	S-L, 200/200V, 3A, 30W, <1/2,5µs	22a	Shi	TIP75(A..C), 2SD422..423
2SC2127(A)	Si-N	S-L, 200/200V, 10A, 100W, <1/3µs	23a	Shi	BUX17(A..C), BUY18, TIP160..162, ++
2SC2128(A)	Si-N	S-L, 200/200V, 30A, 200W, <1/3µs	68a	Shi	2SC1301, 2SC2249, 2SC2445, 2SC2940, ++
2SC2129	Si-N	=2SC2130: ra	7b	Mit	2SC1775(A), 2SC2240, 2SC2390, 2SC2459, ++
2SC213	Si-N	=2SC210: 1,5W	2a	Fui	(BD137, BD228, 2SD1200, 2SD1378, ++)
2SC2130	Si-N	Uni, 70V, 0,1A, 0,2W, 100MHz	7b	Mit	BC174, BC190, BC546, 2SC3245(A), ++
2SC2131	Si-N	UHF-Tr/E, 40V, 0,6A, PQ=1,6W(500MHz)	2a(E=case)	Mit	BLX65, MRF629, 2SC2762, 2SC3185
2SC2132	Si-N	UHF-L, 35V, 9A, PQ=30W(470MHz)	≈57s	Mit	BLU45/12, MRF648
2SC2133	Si-N	VHF-L, 55V, 5A, PQ=34W(220MHz)	≈57s	Mit	—
2SC2134	Si-N	UHF-L, 55V, 10A, PQ=70W(220MHz)	≈57s	Mit	MRF327
2SC2135	Si-N	S, sym, 4V, 0,05A, 0,14W, B>500	7a	Son	—
2SC2137	Si-N	S-L, 500/400V, 7A, 80W, 6MHz	23a	Tos	BUW34..36, BUX15, TIP56A, 2SC3041, ++
2SC2138	Si-N	=2SC2137: 400/300V	23a		BUW34..36, BUX15, TIP56A, 2SC3041, ++
2SC2139(A)	Si-N	S-L, 500/400V, 10A, 100W	23a	Tos	BUW24..28, BUW34..36, 2SC3046, ++
2SC214	Si-N	=2SC210: 25V, 1,5W	2a	Fui	(BD135, BD226, 2SD1200, 2SD1378, ++)
2SC2140	Si-N	=2SC2139: 500/350V	23a		BUW24..26, BUW34..36, 2SC3046, ++
2SC2141	Si-N	NF/S-L, 140V, 0,5A, 50MHz	13j	Son	2SC1913(A), 2SC2483, 2SC2591..2592, ++
2SC2142	Si-N	UHF, 15V, 0,03A, 0,165W, 4,5GHz	5g	Son	BFQ22, BFQ83
2SC2143	Si-N	UHF, 15V, 0,03A, 0,21W, 4,5GHz	25q	Son	BFQ71, BFQ85, BFR14
2SC2144	Si-N	UHF, 15V, 0,02A, 0,21W, 1,4GHz	25p	Son	2SC2144, 2SC2464, 2SC2466, 2SC2726, ++
2SC2145	Si-N	VHF-Tr/E, 35V, 2A, PQ=3,5W(175MHz)	2a	Mit	BFQ43
2SC2147	Si-N	S-L, 400/400V, 50A, 200W, 5MHz	88a	Sak	2SC2159
2SC2148	Si-N	UHF-A, ra, 30V, 0,05A, 0,25W, 3GHz	51s	Nec	BFQ72, 2SC2844
2SC2149	Si-N	UHF-A, ra, 25V, 0,07A, 0,29W, 5GHz	51s	Nec	BFQ73, 2SC3302

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2SC215	Si-N	=2SC210: 80V, 1,5W	2a	Fui	(BD139, BD230, 2SD1200, 2SD1378,++)
2SC2150	Si-N	UHF-A, ra, 20V, 0,03A, 0,25W, 6GHz	51s	Nec	BFG91, BFP91, BFQ57..58, BFQ74
2SC2151	Si-N	S-L, 600/400V, 15A, 150W, 15MHz	23a	Fui	BUS13(A), BUW45..46, 2SD396, 2SD641,++
2SC2152	Si-N	UHF-L, 36V, 2A, PQ>7W(500MHz)	56q	Mat	—
2SC2153	Si-N	VHF, ra, >450MHz	7a	Mat	BF225, BF314, BF502, BF505, BF507++
2SC2159	Si-N	S-L, 400/400V, 50A, 200W, 5MHz	68a	Sak	2SC2147
2SC216	Si-N	HF/S, 50V, 0,3A, 0,85W, >100MHz	2a	Fui	BQ140..141, BQ300..302, 2N3053,++
2SC2160	Si-N	UHF-Tr/E, 36V, 1A, PQ=1,3W(470MHz)	2a	Fui	BLX65
2SC2161	Si-N	UHF-Tr/E, 38V, 1A, PQ=2,5W(470MHz)	55r	Fui	BLW43, BLW60,
2SC2162	Si-N	UHF-L, 36V, 2A, PQ=5W(470MHz)	55r	Fui	BLW14, BLW44, 2N5946
2SC2163	Si-N	UHF-L, 45V, 5A, PQ=15W(470MHz)	55r	Fui	BLW15, BLX89, 2SQ1338..1339,
2SC2164	Si-N	UHF-L, 45V, 10A, PQ=30W(470MHz)	57s	Fui	BLU45/12, MRF646, 2SQ2783
2SC2165	Si-N-Darl+Di	S, 120V, 5A, 0,8W, B>1000	5	Hit	2SQ1882
2SC2188	Si-N	HF-L, 75V, 4A, PQ>6W(27MHz)	17j	Mit	2SQ1944, 2SQ1969, 2SQ2043, 2SQ2119,++
2SC2167	Si-N	NF/S-L, 150V, 2A, 30W, 20MHz	17j	Sak	BD239D, 2SQ2529, 2SQ2660, 2SD1138,++
2SC2168	Si-N	=2SC2167: 200V	17j		BD239F, 2SQ2660, 2SD760, 2SD1138,++
2SC2169	Si-N	VHF-L, 36V, 4A, 25W, PQ=9W(175MHz)	61s	Fui	—
2SC217	Si-N	=2SC216: 25V	2a	Fui	BQ140..141, BQ300..302, 2N3053,++
2SC2172	Si-N	SMD, 60V, 0,2A	35a	Nec	BCW65..66, 2SC2882
2SC2173	Si-N	UHF-L, 35V, 6A, PQ=28W(470MHz)	55r	Tos	—
2SC2174	Si-N	UHF, 25V, 0,07A, 0,35W, 4,5GHz	52s	Nec	BFP96, 2SC2844, 2SC3302
2SC2175	Si-N	S-L, 350/350V, 10A, 100W	23a	Mit	BUW24..26, BUW34..36, 2SC2625..28,++
2SC2176	Si-N	VHF-L, 50V, 3A, PQ=12W(270MHz)	55r	Tos	BLX95, 2SC2894
2SC2177	Si-N	VHF-L, 50V, 5A, PQ=22W(270MHz)	55r	Tos	2N6105
2SC2178	Si-N	VHF-L, 35V, 3,5A, PQ>15W(175MHz)	59r	Tos	MRF222..223
2SC2179	Si-N	UHF-L, 55V, 6A, PQ=40W(770MHz)	55r	Fui	—
2SC218	Si-N	=2SC216: 60V	2a	Fui	BC140..141, BC300..301, 2N1990,++
2SC2180	Si-N	VHF-L, 35V, 6A, PQ=27W(175MHz)	55r	Tos	BLW20, BLW31, 2N6084
2SC2181	Si-N	VHF-L, 35V, 10A, PQ>40W(175MHz)	59r	Tos	BLW85
2SC2182	Si-N	VHF-L, 65V, 6A, PQ=50W(175MHz)	55r	Tos	BLY94
2SC2183	Si-N	UHF-L, 35V, 4,5A, PQ=16W(470MHz)	55r	Tos	BLW15, BLX69, 2SC1404, 2SC1338
2SC2184	Si-N	AM-L, 60V, 3A, PQ=5W(27MHz)	17j	Fui	2SC1306, 2SC1816, 2SC1909, 2SC2092
2SC2185	Si-N	VHF/UHF-L, 50V, 6A, PQ=30W(275MHz)	57s	Nec	2SC2796, 2SC2895
2SC2188	Si-N	VHF/UHF-L, 50V, 9A, PQ=60W(275MHz)	57s	Nec	MRF327
2SC2188	Si-N	VHF, TV-ZF, 45V, 50mA, 0,6W, 500MHz	9c	Mat	BF225, BF310, BF314, BF502..503,++
2SC2189	Si-N	S-L, 150V, 10A, 60W, <1/4µs	23a	Fid	BD245D, BDX11, 2N3442, 2SD551,++
2SC219	Si-N	VHF/UHF, 20V, 25mA, 600MHz	5g	Fui	BF377..378, BF689, BF783, 2N2857,++
2SC2190	Si-N	S-L, 450V, 5A, 100W, <1,5/5,3µs	23a	Fjd	BUW71, BUXF5327345, TIP57A..58A, 2SC3040,++
2SC2191	Si-N	S-L, 450V, 10A, 100W, <2/5,2µs	23a	Fjd	BUW72, BUW75, BUX14, 2SC3520,++
2SC2192	Si-N	VHF-L, 36V, 5A(ss), PQ>15W(175MHz)	56q	Mat	—
2SC2193	Si-N	Uni, 150V, 0,3A, 0,6W, 150MHz	2a	Oki	2SD413, 2SD624, (BF380, MPS-U10)
2SC2194(A)	Si-N	Uni-L, 60V, 1,5A, 100MHz	13m	Tos	BD517, BD519, BD525, BD527, BD529
2SC2196	Si-N	VHF-Tr/E, 40V, 2A, PQ=4,8W(175MHz)	2a(E=case)	Fui	(2SC2145)
2SC2197	Si-N	VHF-L, 50V, 6A, PQ=30W(160MHz)	55r	Fui	BLW20, BLW31, 2N6084
2SC2196	Si-N	hi-Ueb, hi-beta, 100V, 6A, 40W, B>300	22a	Sak	(2SC2318, 2SC2491)
2SC2199	Si-N	hi-Ueb, hi-beta, 150V, 6A, 60W, B>300	23a	Sak	—
2SC22	Si-N	NF/HF/S-L, 75V, 0,6A, 13W, 110MHz	2a	Nec	(BD139, BD230, BD237, BD830,++)
2SC220	Si-N	=2SC210: 0,7A	2a	Fui	→2SC210
2SC2200	Si-N	S-L, 500/400V, 7A, 40W	22s	Tos	BUT58(A), 2SC2235, 2SC2427, 2SC3039,++
2SC2204	Si-N	S-L, 600/400V, 30A, 250W, <1,5/5µs	88a	Tos	2SC2977, 2SD295
2SC2205	Si-N	Dual, 45V, 0,03A, 0,4W, 2,2GHz	TO-71/6 Pin	Nec	—
2SC2206	Si-N	Uni, ra, 30V, 0,03A, 0,4W, 300MHz	9c	Mat	BC238, BC548, BF240..41, BF254..55++
2SC2207	Si-N	AM-L, 60V, 6A, PQ=14W(27MHz)	17j	Hit	2SC1307
2SC2208	Si-N-Darl+Di	S, 120V, 5A, 0,8W, B>1000	2a	Hit	—
2SC2209	Si-N	NF/S-L, 50V, 1,5A, 10W, 150MHz	14h	Mat	BD137, BD228, BD375, 2SD1177..78,++
2SC221	Si-N	=2SC211: 0,7A	2a	Fui	→2SC211
2SC2210	Si-N	AM-V/M/O/ZF, 90MHz	7c	Say	BF240..241, BF254..255, BF594..595,++
2SC2212	Si-N	VHF/UHF, ra, 1400MHz	7e	Son	BF377..378, BF889, BF783, 2N2857,++
2SC2213	Si-N	UHF, 30V, 0,05A, 0,25W, 2,5GHz	7c	Son	2SC2570(A), 2SC3037, 2SC3337
2SC2214	Si-N	NF/S, 100V, 4A, IW, 140MHz, 75/610ns	2a	Son	BFT33..34, 2N4239, 2N5338..39, 2SC696(A)
2SC2215	Si-N	TV-ZF, re, >400MHz	7f	Tos	BF198, BF225, BF310, BF367, BF596++
2SC2218	Si-N	TV-ZF-E, >300MHz	7f	Tos	BF199, BF224, BF311, BF373, BF959++
2SC2217	Si-N	UHF-A, 20V, 0,06A, 0,58W, 8GHz	51s	Nec	2SC2878, 2SC3062, 2SC3358, 2SC3603
2SC2218	Si-N	UHF-A, 20V, 0,06A, 0,35W, 8GHz	52s	Nec	2SC2876, 2SC3062, 2SC3358, 2SC3603
2SC2219	Si-N	UHF-A, 20V, 0,06A, 0,7W, 8GHz		Nec	—
2SC222	Si-N	=2SC212: 0,7A	2a	Fui	→2SC212

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2SC2220	Si-N	S-L, 500/300V, 30A, 250W, <1,5/5µs	68a	Tos	2SC1300, 2SC1471, 2SC1874, 2SC2444
2SC2221	Si-N	VHF-Tr/E, 25V, 0,75A, PQ>1,6W(175MHz)	2a	Nec	(BFQ42, BFR96, BLW18, BLY61)
2SC2222	Si-N	VHF-L, 25V, 1,5A, PQ>5W(175MHz)	55s	Nec	(BLW19, BLW37, MRF212, 2N5590)
2SC2223	Si-N	SMD, FM/VHF, 600MHz	35a	Nec	BF599, BF799, BFS20, 2SC3015
2SC2224	Si-N	NF/Vid-L, 200V, 0,2A, 10W, 100MHz	13m	Nec	BF381..382, BF815, BF617, MPS-U10
2SC2224A	Si-N	=2SC2224: 250V	13m		BF381..382, BF615, BF617, MPS-U10
2SC2227	Si-N	UHF, 35V, 0,2A, 2,4GHz	5g	Nec	2SC1253, 2SC1356, 2SC1952
2SC2228(Y)	Si-N	Vid, 160V, 0,05A, 0,75W, >50MHz	7c(9mm)	Say	BF297..299, BF422A, 2SC3467..69,++
2SC2228A	Si-N	=2SC2228: 200V	7c(9mm)		BF298..299, BF422A, 2SC3467..69,++
2SC2229	Si-N	NF-Tr, Vid, 200V, 0,05A, 0,8W, 120MHz	7c(9mm)	Tos	BF298..299, BF422A, 2SC3467..69,++
2SC223	Si-N	=2SC213: 1A	2a	Fui	→2SC213
2SC2230(A)	Si-N	NF-Tr, Vid, 200V, 0,1A, 0,8W, >50MHz	7c(9mm)	Tos	BF298..299, BF420A, 2SC3467..69,++
2SC2231(A)	Si-N	TV-NF-E, 200V, 0,2A, 12W, >50MHz	13j	Tos	(BF615, BF617, BF757..759, MPS-U10)
2SC2233	Si-N	HV, 700/400V, 4A, 40W, 8MHz	17c	Tos	BU406..408, 2SD823, 2SD1138, 2SD1159,++
2SC2234	Si-N	VHF-L, 35V, 10A, PQ>40W(175MHz)	55r	Tos	—
2SC2235	Si-N	Uni, 120V, 0,8A, 0,9W, 120MHz	7c(9mm)	Tos	2SC2383, 2SC3226, 2SD667, 2SD1812,++
2SC2235	Si-N	NF-Tr/E, 30V, 1,5A, 0,9W, 120MHz	7c(9mm)	Tos	2SC3328, 2SD1014, 2SD1146, 2SD1207,++
2SC2237	Si-N	HF-L, 35V, 2A, PQ>7,5W(175MHz)	58s	Mit	—
2SC2238	Si-N	NF/S-L, 160V, 1,5A, 25W, 100MHz	17j	Tos	2SC2592, 2SC2660, 2SC2529, 2SD1138,++
2SC2238A	Si-N	=2SC2238: 180V	17j		2SC2592, 2SC2680, 2SC2344, 2SD1138,++
2SC2238B	Si-N	=2SC2238: 200V	17j		2SC2660, 2SD760, 2SD1138
2SC2239	Si-N	=2SC2238:	22a		2SC783, 2SC2529, 2SC2592, 2SD1138,++
2SC224	Si-N	=2SC214: 1A	2e	Fui	→2SC214
2SC2240	Si-N	NF, ra, 120V, 0,1A, 0,3W, 100MHz	7c	Tos	2SC2352, 2SC2389, 2SC2459, 2SC2631..32++
2SC2241	Si-N	NF/Vid-L, 300V, 0,15A, 20W, >50MHz	17j	Tos	2SC1505..1507, 2SC1755..1757, 2SC1905
2SC2242	Si-N	NF/Vid-L, 300V, 0,15A, 25W, 50MHz	17j	Tos	2SC1505..1507, 2SC1755..1757, 2SC1905
2SC2243	Si-N	S-L, 450V, 5A, 100W, <1/3µs	23a	Fjd	BUW71, BUX44..45, TIP57A..58A,++
2SC2244	Si-N	=2SC2243: 8A	23a		BUW72, BUX15, BUX44, TIP57A..58A,++
2SC2245	Si-N	=2SC2243: 10A	23a		BUW24..26, BUW34..38, BUW72,++
2SC2246	Si-N	=2SC2243: 15A	23a		BUV25, BUW44, BUX25, 2SD398, 2SD641++
2SC2247	Si-N	=2SC2243: 40W	22a		BUT56(A), MJE53T, 2SC1665, 2SC2200++
2SC2248	Si-N	=2SC2243: 8A, 40W	22a		BUT56(A), BUY65, MJE13006,++
2SC2249	Si-N	S-L, 250V, 30A, 200W	68a	Fjd	2SC1301, 2SC1873, 2SC2445, 2SD843,++
2SC225	Si-N	=2SC215: 1A	2a	Fui	→2SC215
2SC2250	Si-N	=2SC2249: 450V	68a		2SC1300, 2SC1470, 2SC1874, 2SC2220,++
2SC2251	Si-N	UHF-Tr/E, 45V, 0,5A, PQ=1,6W(900MHz)	55r	FUI	BLX97
2SC2252	Si-N	UHF-Tr/E, 45V, 1A, PQ=4,5W(900MHz)	55r	Fui	—
2SC2253	Si-N	UHF-L, 45V, 2A, PQ=9W(900MHz)	55r	Fui	—
2SC2254	Si-N	UHF-L, 45V, 4A, PQ=12W(900MHz)	55r	Fui	—
2SC2255	Si-N	UHF-L, 45V, 6A, PQ=22W(900MHz)	≈57s	Fui	2SC2044
2SC2256	Si-N	S-L, 200/150V, 15A, 150W, 10MHz	23a	Sak	BDW16, BUX41, 2SD552, 2SD583,++
2SC2257	Si-N	Vid-L, 180V, 0,05A, 80MHz	14h	Mal	BF415, BF458..459, BF469, BF471,++
2SC2257A	Si-N	=2SC2257: 220V	14h		BF415, BF458..459, BF469, BF471,++
2SC2256	Si-N	Vid-L, 250V, 0,1A, 4W, 100MHz	14h	Mat	BF415, BF417, BF456..459, 2SC3417,++
2SC2256A	Si-N	=2SC2258: 300V	14h		BF417, BF459, BF850, 2SC3417..18
2SC2258B	Si-N	=2SC2258: 400V	14h		BF850, 2SC3418
2SC2259	Si-N	Dual, ra, 100V, 0,05A, 0,4W, 150MHz	5-SIP	Mit	—
2SC226	Si-N	=2SC216: 0,7A	2a	Fui	→2SC218
2SC2260	Si-N	NF/S-L, 180V, 8A, 80W, 15MHz	23a	Sak	BD245D, BDX11, 2N3442, 2SD733, 2SD551,++
2SC2261	Si-N	=2SC2260: 180V	23a		MJ15015, BDW245E, BDW14, 2SC2607,++
2SC2262	Si-N	=2SC2260: 200V	23a		MJ15015, BD245F, BDW16, 2SC2607,++
2SC2263	Si-N	Uni, ra, 60V, 0,05A, 0,25W, 70MHz	7c	Mat	2SC2390, 2SC1775(A), 2SC2631..32,++
2SC2264	Si-N	Uni, 80V, 1A, 0,75W, 200MHz	7c(9mm)	Mat	2SC3228, 2SD667, 2SD1292, 2SD1812,++
2SC2265	Si-N	VHF, ra, 550MHz	5g	Hit	BF314, BF502..503, BF505, BF507,++
2SC2266	Si-N	S-L, 500V, 10A, 100W	23a	Hit	BUW25..26, BUW34..38, 2SC3043,++
2SC2267	Si-N	S, Vid, 400/360V, 0,1A, 0,4W, 70MHz	2a	Hit	MPS-A44..45, 2SC3118, 2SC3469, 2SD1350
2SC227	Si-N	=2SC217: 0,7A	2a	Fui	→2SC217
2SC2270	Si-N	S-L, lo-sat, 50V, 5A, 10W, 100MHz	14h	Tos	2SC3420, 2SD826, 2SD1685
2SC2271	Si-N	Vid, 300V, 0,1A, 0,9W, >50MHz	7c(9mm)	Say	2SC3468..3469, (MPS-U10, 2SC4019,++)
2SC2272	Si-N	UHF, ra, 20V, 0,035A, 0,44W, 10GHz	52s	Nec	2SC3584, 2SC3586..3587
2SC2273	Si-N	UHF, ra, 25V, 0,065A, 0,44W, 8,5GHz	52s	Nec	2SC3062
2SC2274	Si-N	Uni, 60V, 0,5A, 0,6W, 120MHz	7c	Say	BC637, BC639, 2N3700..01, 2SD667,++
2SC2274K	Si-N	=2SC2274: 100V	7c		BC639, 2N3700..01, 2SC1670, 2SD667,++
2SC2275	Si-N	NF/HF-L, 120V, 1,5A, 25W, 200MHz	17j	Nec	2SC2238, 2SC2526..2529, 2SD608(A),++
2SC2275A	Si-N	=2SC2275: 150V	17j		2SC2238, 2SC2529, 2680, 2SD608(A),++
2SC2276	Si-N	NF/HF/S-L, 130V, 7A, 80W, 100MHz	19j	Nec	2SD566, 2SD848A

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2SC2277	Si-N	Uni, 50V, 0,5A, 0,625W, 120MHz	7e	Hit	BC337, BC637, BC639, 2SD667, ++
2SC2278	Si-N	Vid-L, 300V, 0,1A, 80MHz	17m	Hit	BF382, BF461..462, MPS-U10, 2SC1758, ++
2SC2279	Si-N	Vid-L, 300V, 0,1A, 10W, 35MHz	13m	Tos	BF382, BF461..462, MPS-U10, 2SC1758, ++
2SC228	Si-N	=2SC218: 0,7A	2a	Fui	→2SC218
2SC2280	Si-N	HF-L, -/18V, 0,75A, 10W	55r	Nec	—
2SC2281	Si-N	VHF-L, 38V, 1,5A, PQ>7,1W(175MHz)	55r	Nec	BLW19, BLW37, MRF212, 2N5590
2SC2282	Si-N	VHF-L, 38V, 3A, PQ>15W(175MHz)	55r	Nec	BLY89, MRF209, 2N5591, 2N6082
2SC2283	Si-N	UHF-Tr/E, 38V, 0,75A, PQ>2,8W(500MHz)	58r	Nec	2SC3020
2SC2284(A)	Si-N	UHF-L, 38V, 1,5A, PQ>7,1W(500MHz)	58r	Nec	2SC3021
2SC2285(A)	Si-N	UHF-L, 38V, 3..4A, PQ>14,1W(500MHz)	58r	Nec	—
2SC2286	Si-N	VHF-Tr/E, 38V, 0,75A, PQ>2,5W(175MHz)	58r	Nec	—
2SC2287	Si-N	VHF-L, 38V, 1,5A, PQ>7,1W(175MHz)	58r	Nec	—
2SC2287M	Si-N	=2SC2287:	=58r		—
2SC2288	Si-N	VHF-L, 38V, 3A, PQ>15W(175MHz)	58r	Nec	2SC2094
2SC2288M	Si-N	=2SC2288:	=58r		—
2SC2289	Si-N	VHF-L, 25V, 1,5A, PQ>5W(175MHz)	58r	Nec	—
2SC2289M	Si-N	=2SC2289:	=58r		—
2SC229	Si-N	NF/S-L, 80V, 1A	2a	Fui	(BD139, BD230, 2SD1200, 2SD1378, ++)
2SC2290	Si-N	AM-SSB-L, 45V, 20A, PEP=60W(28MHz)	59r	Tos	MRF421, MRF454
2SC2291	Si-N	Dual, 100V, 0,1A, 0,4W, 100MHz	5-SIP	Mit	—
2SC2292	Si-N	S-L, 500/400V, 8A, 80W, 20MHz	23a	Shi	BUW25..28, BUW34..38, 2SC3046, ++
2SC2293	Si-N	=2SC2292: 10A, 100W	23a		BUW25..28, BUW34..36, 2SC3046, ++
2SC2294	Si-N	FM, 300MHz	7c	Mat	BF225, BF310, BF314, BF502, BF505++
2SC2295	Si-N	SMD, AM/FM, ra, 30V, 0,03A, 250MHz	35a	Mat	BC849..850, BF554, BF840..841
2SC2296	Si-N	HF, 30V, 0,03A, 0,2W, 230MHz	7c	Mit	BC238, BC548, BF240..41, BF254..55++
2SC2297	Si-N	AM-L, 55V, 8A, PQ>16W(27MHz)	17j	Hit	2SC1817
2SC2298(A,B)	Si-N-Darl	NF/S-L, 30V, 1A, 8W, B>4000	14b(A)	Hit	BD477A,B, BD875, 2SC4340..41
2SC2299	Si-N	Uni, 20V, 1A, 0,5W, 150MHz	7c	Fui	BC337..38, BC635, BC637, BC639, ++
2SC23	Si-N	=2SC22: 0,5A	2a	Nec	(BD139, BD230, BD237, BD830, ++)
2SC230	Si-N	HF/S, 80V, 0,2A, 0,35W, 350MHz	2a	Fui	BSW63..64, 2N2221A..2222A
2SC2300	Si-N	=2SC2299: 50V	7c		BC337, BC635, BC637, BC639, ++
2SC2301	Si-N	UHF-L, 45V, 2,8A, PQ=16W(890MHz)		Nec	—
2SC2302	Si-N	S-L, 500/400V, 7A, 40W, 35MHz	22a	Sak	BUT58(A), 2SC2427, 2SC2739, 2SC3039,
2SC2303	Si-N	S-L, 500/400V, 10A, 80W, 35MHz	23a		BUW25..28, BUW34..38, 2SC3046, ++
2SC2304	Si-N	S-L, 500/400V, 12A, 100W, 35MHz	23a		BUW44, BUW75..77, BUX25, 2SC3043, +
2SC2305	Si-N	S-L, 400/400V, 7A, 80W	18j	Sak	BU426(A), BU926, TIP57A..58A, ++
2SC2306	Si-N	S-L, 450/400V, 15A, 150W, 7MHz	23a	Sak	BUV25, BUW44..45, BUX25, 2SD641, ++
2SC2307	Si-N	S-L, 500/400V, 12A, 100W, 18MHz	18j	Sak	BUV46(AC), BUW13(A), 2SC3520, ++
2SC2308	Si-N	Uni, 55V, 0,1A, 0,2W, 230MHz, B>100	7c	Hit	BC187, BC182, BC237, BC547, ++
2SC2309	Si-N	=2SC2308: B>250	7c		BC187, BC182, BC237, BC547, ++
2SC231	Si-N	NF/S, 50V, 0,7A, 0,85W	2a	Fui	BC140..141, BC300..302, 2N3053, ++
2SC2310	Si-N	=2SC2308: ra	7c		BC414, BC550, 2SC2240, 2SC2459, ++,
2SC2311	Si-N	S-L, 50V, 1A, 45/90ns	14h	Fui	BD137, BD228, BD375, 2SD1177..78, ++
2SC2312	Si-N	HF-L, 80V, 8A, PQ=18,5W(27MHz)	17j	Mit	2SC1307, 2SC1944, 2SC1969, 2SC1817, ++
2SC2313	Si-N	AM/FM-L, 40V, 10A, PQ=38W(85MHz)	55r	Mit	—
2SC2314	Si-N	AM-L, 75V, 1A, PQ=1,8W(27MHz)	14h	Say	—
2SC2315	Si-N	hi-beta, 80V, 6A, 40W, B=800	17j	Sak	2SC2316, 2SC2491, 2SD1158
2SC2316	Si-N	=2SC2315: 100V	17j		2SC2318, 2SC2491
2SC2317	Si-N	hi-beta, 200V, 1A, 30W, B=1000	17j	Sak	2SD1272
2SC2318	Si-N	VHF/UHF-A/E, 40V, 0,35A, 2700MHz	5q	Tos	2SC1199, 2SC1252, 2SC1395..86, 2SC2852
2SC2319	Si-N	VHF/UHF-A/E, 40V, 0,35A, 2900MHz	55r	Tos	2N5944
2SC232	Si-N	=2SC231: 25V	2a	Fui	BC140..141, BC300..302, 2N3053, ++
2SC2320	Si-N	Uni, 50V, 0,2A, 0,3W, 200MHz	7c	Mit	BC187, BC162, BC237, BC547, ++
2SC2320L	Si-N	=2SC2320: ra	7c		BC414, BC550, 2SC2240, 2SC2459, ++
2SC2321	Si-N	NF/S-L, 130V, 8A, 80W, 60MHz	23a	Fui	2SC1584, 2SD1047, 2SD425, 2SD551, ++
2SC2322	Si-N	NF/S-L, 120V, 12A, 120W, 60MHz	23a	Fui	2SC1584, 2SD1047, 2SD425, 2SD551, ++
2SC2323	Si-N	=2SC2322: 150V	23a		2SC1584, 2SD1047, 2SD733, 2SD551, ++
2SC2324	Si-N-Darl	NF/S-L, 80V, 1A, 8W, B>2000	14b(A)	Hit	BD877, BD875, BDX42..44, 2SD985..86++
2SC2325	Si-N	HF-L, 45V, 0,6A, PQ>1,3W(4,2GHz)	82a	Nec	—
2SC2326	Si-N	HF-L, 45V, 1,2A, PQ>2,5W(4,2GHz)	82a	Nec	—
2SC2327	Si-N	UHF, ra, 20V, 0,03A, 4,5GHz	24b	Tos	BFQ89, BFR91
2SC2328	Si-N	Mm, UHF, ra, 20V, 0,03A, 2,2GHz	24b	Tos	BFT24, BFR34, BFW93
2SC2329	Si-N	VHF-ATr/E, 38V, 0,75A, PQ>2W(175MHz)	2a	Nec	BFS22, BFW46, BLY33, MRF237, 2N3924
2SC233	Si-N	=2SC231: 80V	2a	Fui	BC140..141, BC300..301, 2N1990, ++
2SC2330	Si-N	VHF-L, 38V, 8A, PQ>31,6W(175MHz)	58r	Nec	—
2SC2331	Si-N	S-L, 150V, 2A, 15W, <0,5/2µs	17j	Nec	BD239F, 2SC2680, 2SD780, 2SD1138, ++

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2SC2333	Si-N	S-L, 500/400V, 2A, 15W, <1/3,5µs	17j	Nec	BUV36(A), BUX84..85, 2SC2534, 2SC2736
2SC2334	Si-N	S-L, 150V, 7A, 40W, <0,5/2µs	17j	Nec	BD243F, BU409, BUW64C, TIP150..152
2SC2335	Si-N	S-L, 500/400V, 7A, 40W, <1/3,5µ	17j	Nec	BUT56(A), 2SC2427, 2SC2739, 2SC3039
2SC2336	Si-N	NF/HF-L, 180V, 1,5A, 25W, 95MHz	17j	Nec	2SC2238A,B, 2SC2660, 2SD608A, 2SD780
2SC2336A	Si-N	=2SC2336: 200V	17j		2SC2236B, 2SC2660, 2SD610, 2SD760
2SC2336B	Si-N	=2SC2336: 250V	17j		2SC2023, 2SD610
2SC2337(A)	Si-N	NF/S-L, 150V, 10A, 100W, 70MHz	23a	Nec	BDX11, 2SD1047, 2SD551, 2SD733, ++
2SC2336	Si-N	UHF-O, 25V, 0,04A, PQ=0,14W(7,5GHz)	52s	Nec	2SC3584, 2SC3586..3587
2SC2339	Si-N	UHF-O, 25V, 0,15A, PQ=0,2W(6GHz)	55s	Nec	—
2SC234	Si-N	NF/S-L, 100V, 1,5A, 18W, 140MHz	2e	Fui	(BD139, BD230, BD379, 2SD1177..1178
2SC2340	Si-N	UHF-Tr/E, 30V, 0,3A, 6W, 6,5GHz	82d	Nec	—
2SC2341	Si-N	UHF-O, 25V, 0,04A, PQ=0,14W(7,5GHz)		Nec	—
2SC2342	Si-N	UHF-O, 25V, 0,15A, PQ=0,2W(6GHz)		Nec	—
2SC2344	Si-N	NF/S-L, 180/180V, 1,5A, 25W, 100MHz	17j	Say	2SC2238A,B, 2SC2660, 2SD608A
2SC2345	Si-N	UHF, ra, re, 25V, 0,02A, 980MHz	=42	Tos	(2SC2484..66, 2SC2360, 2SC2726, ++)
2SC2347	Si-N	VHF-M, UHF-O, >650MHz	7c	Tos	BF377..378, BF689, BF763, 2N2857, ++
2SC2348	Si-N	VHF-V, re, >400MHz	7l	Tos	BF314, BF496, BF502, BF505, BF507++
2SC2349	Si-N	VHF-O, >600MHz	7c	Tos	BF199, BF224, BF311, BF503, BF505++
2SC235	Si-N	=2SC234: 120MHz	2a	Fui	(BD139, BD230, BD379, 2SD1177..1178
2SC2350	Si-N	SMD, UHF, ra, 30V, 0,05A, 2,8GHz	35a	Nec	BFR53, 2SC3014
2SC2351	Si-N	SMD, UHF, ra, 25V, 0,07A, 4,5GHz	35a	Nec	2SC3161
2SC2352	Si-N	VHF, 850MHz	7f	Nec	BF225, BF310, BF314, BF505, BF507++
2SC2353	Si-N	UHF, 2,3GHz	25p	Nec	2SC2466, 2SC2728
2SC2354	Si-N	NF/S-L, 300V, 1A, 30W, 20MHz	22a	Sak	BUX67A..C, TIP47..50, 2SC782, 2SD859++
2SC2356	Si-N	S-L, 500/400V, 10A, 100W, 20Mhz	23a	Fui	BUW25..28, BUW34..36, 2SC3046, ++
2SC2357	Si-N	S-L, 1000/700V, 10A, 150W	23a	Fui	BUS12A, BUX81, BUY69A..70A, MJ8504++
2SC2358	Si-N	=2SC2357: 1000/800V	23a		BUS12A, BUX81, BUY69A..70A, MJ8504++
2SC2359	Si-N	S-L, 450/400V, 4A, 40W, 20MHz	22a	Fui	BUT93, BUX64, MJE53T, TIP75B,C, ++
2SC236	Si-N	=2SC234: 90V, 100MHz	2a	Fui	(BD139, BD230, BD379, 2SD1177..1178
2SC2360	Si-N	UHF, 30V, 20mA, 0,2W, 1100MHz	25p	Mat	2SC2464, 2SC2466, 2SC2353, 2SC2728
2SC2361	Si-N	NF/S-L, 70V, 4A, 25W, 70MHz	17j	Mat	BDV10..12, MJE15028, 2SC3253, 2SD772++
2SC2361A	Si-N	=2SC2361: 100V	17j		BDV10..12, MJE15028, MJE15030, 2SD772
2SC2362	Si-N	Uni, ra, 120V, 0,05A, 0,4W, 130MHz	7c	Say	2SC1845, 2SC2088, 2SC2240, 2SC2389, ++
2SC2362K	Si-N	=2SC2362: 150V	7c		2SC2831..32
2SC2363	Si-N	NF-Tr, 120V, 0,05A, 0,5W, 130MHz	7c	Say	2SC1890A, 2SC2375, 2SC3245, 2SD756A
2SC2364	Si-N-Darl	S-L, 200V, 5A, 80W, B=1000	16c	Sak	2SD921, 2SD933, 2SD1090, 2SD1122, ++
2SC2365	Si-N	S-L, 800V, 6A, 50W, 10MHz	23a	Sak	BU326, BU428, BU526, BUX47(A), ++
2SC2366	Si-N	S-L, 500/400V, 40A, 300W, 15MHz	66a	Fui	2SC1435, 2SD642
2SC2367	Si-N	UHF-A, ra, 20V, 0,08A, 0,58W, 8GHz	51e	Nec	BFQ66, 2SC3603
2SC2368	Si-N	UHF, 30V, 0,05A, 0,25W, 2,8GHz	25q	Nec	2SC2368, 2SC2470, 2SC3368
2SC2369	Si-N	UHF, 25V, 0,07A, 0,25W, 4,5GHz	25q	Nec	BFP96, BFQ73, 2SC2844, 2SC3302
2SC237	Si-N	VHF-ATr, 25V, 0,3A, 0,35W, 450MHz	2a	Fui	2SC2851, (BFX55)
2SC2370	Si-N	UHF-Tr/E, 35V, 0,8A, PQ=4W(470MHz)	51r	Tos	—
2SC2371	Si-N	Vid-L, TV-HA/VA-Tr, 300V, 0,1A, 10W	14h	Nec	BF417, BF459, 2SC3417, 2SC3503
2SC2373	Si-N	TV-HA, 200/100V, 7,5A, 40W, 10MHz	17j	Nec	BU406..408, 2SC3189, 2SC3589, 2SD1069++
2SC2375	Si-N	NF-Tr, 150V, 0,05A, 0,9W, 130MHz	7c(9mm)	Say	2SC2632, 2SC3245(A), 2SC3248, 2SC3800, ++
2SC2376	Si-N	TV-NF-E, TV-HA-Tr, 300V, 0,15A, 20W	14h	Tos	MJE340, MJE3439..3440, 2SC2899
2SC2377	Si-N	AM/FM/VHF, 30V, 15mA, 0,4W, 850MHz	9c	Mat	BF225, BF310, BF314, BF502, BF505++
2SC2378	Si-N	NF, 70V, 0,1A, 0,25W, 250MHz	7c	Nec	BC174, BC546, 2SC2240, 2SC3245(A), ++
2SC2379	Si-N	UHF-L, 35V, 1,4A, PQ>6W(470MHz)	59r	Tos	—
2SC238	Si-N	NF/HF, 40V, 0,1A, 0,65W, 350MHz	2a	Fui	BFW16..17, BFX55, 2N3724, 2SC1385, ++
2SC2380	Si-N	UHF-L, 35V, 2,8A, PQ>12W(470MHz)	59r	Tos	—
2SC2381	Si-N	UHF-L, 35V, 6A, PQ>25W(470MHz)	59r	Tos	—
2SC2382	Si-N	VHF-L, 40V, 12A, PQ>50W(175MHz)	59r	Tos	MRF243
2SC2383	Si-N	CTV-NF/VA, 180V, 1A, 0,9W, >20MHz	7c(9mm)	Tos	2SC3228, 2SD1812
2SC2384	Si-N	=2SC2383: 10W	13m		(2SC1913, 2SC2592, 2SD367(A), 2SD1136)
2SC2385	Si-N	Uni, ra, 70V, 0,1A, 0,2W, 130MHz	7b	Mit	2SC1775(A), 2SC2240, 2SC2390, 2SC2459, ++
2SC2386	Si-N	Uni, 70V, 0,3A, 0,5W, 125MHz	7b	Mit	BC846, BC639, 2SC4414, 2SD1226, ++
2SC2387	Si-N	S-L, 500V, 8A, 100W	23a	Hit	BUW25..26, BUW34..36, 2SC3046, ++
2SC2388	Si-N	S-L, 450/400V, 4A, 75W, 20MHz	23a	Fui	BU326, BU428, BUX45, 2SC3083, ++
2SC2388A	Si-N	=2SC2388: 500/400V, 7A	23a		BU326, BU426, BUX15, 2SC2536, ++
2SC2389(S)	Si-N	Uni, ra, 120V, 0,05A, 0,3W, 140MHz	7c, 41c	Rhm	2SC1845, 2SC2088, 2SC2240, 2SC2459, ++
2SC239	Si-N	S, 50V, 0,3A, 0,35W, 450MHz, <-/150ns	2a	Fui	BSS10, BSX19..20, BSX39, 2N3261, ++
2SC2390	Si-N	=2SC2389: 80V	7c	Rhm	2SC1845, 2SC2089, 2SC2240, 2SC2459, ++
2SC2391	Si-N	UHF-Tr/E, 35V, 0,6A, PQ>3W(470MHz)	59r	Tos	—
2SC2392	Si-N	UHF-L, 35V, 2,8A, PQ>15W(470MHz)	59r	Tos	—

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2SC2393	Si-N	AM-L, 80V, 4A, PQ>6W(28MHz)	17j	Tos	2SC1818, 2SC2119
2SC2394	Si-N	AM-L, 45V, 6A, PQ=16W(50MHz)	17j	Tos	2SC2050
2SC2395	Si-N	AM-L, 40V, 5A, PEP=10W(28MHz)	59r	Tos	2SC2693
2SC2396	Si-N	Uni, 60V, 0,1A, 0,4W, 90MHz	7c	Hit	BC174, BC182, BC190, BC546, ++
2SC2397	Si-N	AM-L, 80V, 6A, PQ>18W(27MHz)	17j	Hit	2SC1817
2SC2398	Si-N	NF/S-L, 100V, 10A, 95W, 80MHz	23a	Son	2SC2681, 2SC2706, 2SC2837
2SC2399	Si-N	VHF/UHF, 940MHz	7e	Hit	BF377..378, BF689, BF763, 2N2857, ++
2SC24	Si-N	=2SC22: 100V, 0,5A	2a	Nec	(BD139, BD230, BD237, BD830, ++)
2SC240	Si-N	S-L, 100V, 5A, 75W	23a	Nec	BD245C, BDV95, BDX95, 2N5758..80, ++
2SC2400	Si-N	SS, 40V, 0,1A, 0,31W, <10/15ns	7e	Hit	BSV91..92, BSX92..93, 2N2368..69(A), ++
2SC2401	Si-N-Darl	Uni, 40V, 0,3A, 0,31W, B=10000	7e	Hit	BC517, BC817, BC875, MPS-A25..29, ++
2SC2402	Si-N	S-L, 300/200V, 15A, 150W, -/2,3µs	23a	Fui	BUX13, BUY50, MJ15022, MJ15024, ++
2SC2403	Si-N	S-L, 300/200V, 40A, 300W, -/3µs	68a	Fui	2SC2368, 2SC2973, 2SD702
2SC2404	Si-N	=2SC2377: SMD	35a	Mnt	BF599, BF799, BFS20, 2SC3015, ++
2SC2405	Si-N	SMD, ra, 35V, 0,05A, 200MHz	35n	Mat	BC849..850, BCF32..33, BCF81
2SC2406	Si-N	=2SC2405: 55V	35a		BC850, BCF81
2SC2407	Si-N	UHF-O, 35V, 0,15A, PQ=0,16W(500MHz)	7t	Nec	2SC1954
2SC2408	Si-N	HF-A, 35V, 0,15A, 0,6W, 3,5GHz	7t	Nec	2SC3337
2SC2409	Si-N	NF, ra, 50V, 0,1A, 0,3W, 180MHz	7c	Rhm	BC184, BC414, BC550, 2SC2240, ++
2SC241	Si-N	=2SC240: 80V	23a	Nec	BD245A, BDV91, BDX91, 2N4914..15, ++
2SC2410(S)	Si-N	HF, 40V, 0,1A, 0,25W, 230MHz	7c, 41c	Rhm	BF240..241, BF254..255, BF594..595, ++
2SC2411	Si-N	SMD, 40V, 0,5A, 250MHz	≈35d	Rhm	—
2SC2411K	Si-N	=2SC2411:	35a		BC817, BCW65..66, BCX19, 2SC3325, ++
2SC2412	Si-N	SMD, 50V, 0,15A, 180MHz	≈35d	Rhm	—
2SC2412K	Si-N	=2SC2412:	35a		BC847, BCW71..72, BCW81
2SC2412KLN	Si-N	=2SC2412: rn	35a		BC850, BCF81
2SC2412LN	Si-N	=2SC2412: ra	≈35d		—
2SC2413	Si-N	SMD, HF, 40V, 0,05A, 300MHz	≈35d	Rhm	(BF817..18, BF554, BF840..841)
2SC2413K	Si-N	=2SC2413:	35a		BFS17..18, BF554, BF840..841
2SC2414	Si-N	S-L, 500V, 2A, 70W, <1/3,5µs	23a	Mat	BU126, BUX45..46, TIP54, 2SC3083, ++
2SC2415	Si-N	=2SC2414: 7A, 90W	23a		BU326, BU426, BUX45, 2SC3041, ++
2SC2418	Si-N	=2SC2414: 10A, 120W	23a		BUW25..26, BUW34..36, 2SC3046, ++
2SC2417	Si-N	Min, UHF, -/10V, 0,03A, 0,25W, 6,5GHz	24	Tos	BFQ57..58, BFQ65, BFQ74, 2SC3276, ++
2SC2418	Si-N	Min, UHF, -/8V, 0,06A, 0,33W, 7GHz	24	Tos	2SC2876, 2SC3358, 2SC3603
2SC2419	Si-N	VHF-Tr/E, 85V, 1A, PQ>2,5W(175MHz)	2a(E=case)	Tos	BFS23, BLY34
2SC242	Si-N	=2SC240	23a	Nec	BD245C, BDV93, BDX93, 2N5758..80, ++
2SC2420	Si-N	VHF-L, 40V, 6A, PQ>32W(175MHz)	55r	Tos	2N6084
2SC2421	Si-N-Darl	NF/S-L, 200V, 5A, 100W, 30MHz, B=700	23a	Fui	2SD776, 2SD920..921, 2SD929, 2SD1090, ++
2SC2422	Si-N-Darl	=2SC1421: 150V	23a		2SD776, 2SD920..923, 2SD929, 2SD1090, ++
2SC2423	Si-N-Darl	=2SC1421: 40W	22a		2SD930, 2SD1023, 2SD1025
2SC2424	Si-N-Darl	=2SC1421: 150V, 40W	22a		2SD930, 2SD1023, 2SD1025, 2SD1128, ++
2SC2425	Si-N	NF/Vid-L, 300/200V, 0,1A, 20MHz	17j	Fui	2SC1505..1507, 2SC1755..1758, 2SC1905
2SC2427	Si-N	S-L, 500/400V, 7A, 40W, 20MHz	17j	Fui	BUT56(A), TIP150..152, 2SC2335, ++
2SC2428	Si-N	S-L, Reg-L, 180V, 12A, 120W, 80MHz	23a	Fui	MJ15015, BDW14, BDY56, 2SC2608, ++
2SC2429	Si-N	S-L, Rag-L, 450/400V, 15A, 150W, 30MHz	23a	Fui	BUV25, BUW44, BUX25, 2SD641, ++
2SC2429A	Si-N	=2SC2429: 600/450V	23a		BUS13(A), BUW45..46, 2SD641, ++
2SC243	Si-N	=2SC240: 140V	23a	Nec	BD245D, 2N4347, 2N5780, 2SD731, 2SD1046++
2SC2430	Si-N	S-L, 120V, 10A, 100W, 80MHz	23a	Fui	BUW70, 2SC1584..1585, 2SC2706, 2SD552++
2SC2431	Si-N	S-L, 120V, 15A, 100W, 80MHz	23a	Fui	BUX41, 2SC1584..1585, 2SC2706, 2SD552++
2SC2432	Si-N	S-L, 70V, 15A, 100W, 80MHz	23a	Fui	BUX41, 2SC1584..1585, 2SC2706, 2SD552++
2SC2433	Si-N	S-L, 120V, 30A, 150W, 80MHz	23a	Fui	BDW30, BUW39, BUX39, 2N6275..77, ++
2SC2434	Si-N	=2SC2433: 70V	23a		BDY29, BUW39, BUX39, 2N6275..77, ++
2SC2435	Si-N-Darl	S-L, 300V, 8A, 100W, B>2000	23a(G)	Fui	BDX85B, BDX83C, MJ4035, 2SD729, ++
2SC2436	Si-N-Darl	=2SC2435: 10A	23a(G)	Fui	BDX67B, MJ4035, 2SD729, ++
2SC2437	Si-N	S-L, 450V, 7A, 100W	23a	Fjd	BUX15, BUX44, TIP57A..58A, 2SC3041, ++
2SC2436	Si-N	S-L, 150V, 7A, 50W, <500/3000ns	17j	Fjd	BU406..406, BUW64A..C, MJE15030, ++
2SC2439	Si-N	S-L, 150V, 7A, 50W, <500/3000ns	17j		BU406..408, BUW64A..C, MJE15030, ++
2SC244	Si-N	=2SC240: 80V	23a	Nec	BD245A, BDV91, BDX91, 2N4914..15, ++
2SC2440	Si-N	S-L, 450V, 5A, 40W	17j	Fjd	MJE53T, 2SC2518, 2SC2542, 2SC3497, ++
2SC2441	Si-N	NF-Tr-L, 180V, 0,06A, 150MHz	14h	Say	BF415, BF417, BF469, BF471, ++
2SC2442	Si-N	S-L, 600V, 30A, 200W, <2/8µs	88a	Fjd	2SC2204, 2SC2977, 2SD295, 2SD644, ++
2SC2443	Si-N	S-L, 600V, 50A, 400W	≈74	Fjd	—
2SC2444	Si-N	S-L, 500/400V, 30A, 250W, <1,5/4µs	68a	Tos	2SC1300, 2SC1471, 2SC1874, 2SC2220, ++
2SC2445	Si-N	S-L, 300/200V, 30A, 250W, <1/3µs	68a	Tos	2SC1299, 2SC1873, 2SD542..543, 2SD643, ++
2SC2447	Si-N	UHF, 20V, 0,05A, 0,25W, 1600MHz	5q	Mat	BFR37, BFS55, BFW30, BFX73
2SC2448	Si-N	S-L, 650V, 7A, 80W, <1/4µs	23a	Fjd	BU526, BU926, BUX47, 2SC3092, ++

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2SC2449	Si-N	S-L, 650V, 7A, 80W, <1/2,5µs	23a	Fjd	BU526, BU926, BUX47, 2SC3092, ++
2SC245	Si-N	=2SC240: 120V	23a	Nec	BD245C, 2N5759..60, 2SD718, 2SD896, ++
2SC2450	Si-N	=2SC2448: 750/700V	23a		BU526, BU926, BUX47, 2SC3092, ++
2SC2451	Si-N	=2SC2449: 750/700V	23a		BU526, BU926, BUX47, 2SC3092, ++
2SC2452	Si-N	=2SC2448: 850/800V	23a		BU526, BU926, BUX47, 2SD811, ++
2SC2453	Si-N	=2SC2449: 850/800V	23a		BU526, BU926, BUX47, 2SD811, ++
2SC2454	Si-N	VHF, TV-ZF, 550MHz	25q	Mat	2SC2467, 2SC2727, 2SC2729
2SC2455	Si-N	VHF-V, >450MHz	25p	Mat	(2SC2727, 2SC2729)
2SC2456	Si-N	Vid-E, TV-HA-Tr, 300V, 0,1A, 10W	14h	Tos	BF417, BF459, 2SC3417, 2SC3503, ++
2SC2458(L)	Si-N	Uni, ra, 50V, 0,15A, 0,2W, >80MHz	41c	Tos	BC184, BC414, BC550, 2SC2240, ++
2SC2459	Si-N	Uni, 120V, 0,1A, 0,2W, 100MHz	41c	Tos	2SC1845, 2SC2240, 2SC2389, 2SC3245(A), ++
2SC246	Si-N	=2SC240: 180V	23a	Nec	BD245E, BU608, 2SC2261..2262, 2SD751
2SC2460	Si-N	NF/S-L, 140V, 12A, 100W, 90MHz	23a	Tos	BDW10, 2SD425, 2SD551, 2SD1047, ++
2SC2460A	Si-N	=2SC2460: 120W	23a		BDW10, BDW14, 2SD424..425, 2SD551, ++
2SC2461	Si-N	NF/S-L, 150V, 15A, 150W	23a	Tos	2SC1584..1585, 2SC2608, 2SD424, ++
2SC2461A	Si-N	=2SC2460: 160V	23a		2SC1585..1586, 2SC2608, 2SD424, ++
2SC2462	Si-N	SMD, 50V, 0,1A, 230MHz	35a	Hit	BC846..847, BCW71..72, BCW81, ++
2SC2463	Si-N	=2SC2462: 55V	35a		BC848, BCV71..72, 2SC3323, ++
2SC2464	Si-N	UHF-V, TV-Tuner, 30V, 20mA, 900MHz	25p	Hit	2SC2466, 2SC2144, 2SC2360, 2SC2726
2SC2465	Si-N	VHF-V, TV-Tuner, 20V, 20mA, 550MHz	25q	Hit	2SC2470, 2SC2388
2SC2466	Si-N	UHF-M, TV-Tuner, 30V, 50mA, 2,2GHz	25p	Hit	2SC2353, 2SC2728
2SC2467	Si-N	VHF-M, TV-Tuner, 30V, 50mA, 800MHz	25q	Hit	2SC2454, 2SC2727, 2SC2729
2SC2468	Si-N	VHF-M/O, TV-Tuner, 30V, 50mA, 900MHz	24b	Hit	BF382..383, BFW93
2SC2469	Si-N	VHF-M/O, TV-Tuner, 30V, 50mA, >800MHz	24b	Hit	BF382..383, BFW93
2SC247	Si-N	Uni, 100V, 0,1A, 0,8W, 150MHz	2a	Fui	BF257..259, 2SC2240, 2SC3245(A), ++
2SC2470	Si-N	VHF, 30V, 0,05A, 0,2W, 2,2GHz	25q	Hit	2SC2353, 2SC2368
2SC2471	Si-N	UHF-O, 30V, 0,05A, 0,31W, 2GHz	7t	Hit	BF357, 2SC2570(A), 2SC3037
2SC2472	Si-N	UHF, ra, 30V, 0,05A, 0,3W, 2,2GHz	7f	Hit	BF357, 2SC2570(A), 2SC3037
2SC2473	Si-N	VHF, ra, 30V, 0,05A, 0,3W, 2,2GHz	7t	Hit	BF357, 2SC2570(A), 2SC3037
2SC2474	Si-N	S, 60V, 0,2A, 0,6W, <70/250ns	7e	Nec	BSV59, BSX49, 2N2221..22, 2N3903..04++
2SC2475	Si-N	S, 60V, 0,6A, 0,6W, <35/285ns	7e	Nec	BSV59, BSX49, 2N2221..22, 2N3301..02++
2SC2476	Si-N	S, 30V, 0,2A, 0,6W, <70/250ns	7e	Nec	BSW41, BSY63, 2N708, 2N914, 2N4123, ++
2SC2477	Si-N	S, 80V, 0,6A, 0,6W, <35/300ns	7e	Nec	BSX48, BSX87..88, BSX97, 2N914, ++
2SC248	Si-N	Uni, 70V, 0,05A, 0,3W, 170MHz	2a	Fui	BC546, 2SC1775(A), 2SC1890(A), 2SD755++
2SC2480	Si-N	SMD, VHF/UHF, 30V, 50mA, 1300MHz	35a	Mat	BFS17, 2SC3005, 2SC3016, 2SC3161
2SC2481	Si-N	TV-VA, NF/S-L, 150V, 1,5A, 20W, >20MHz	14h	Tos	2SC3117, 2SD869
2SC2482	Si-N	Vid, TV-HA-Tr, 300/300V, 0,1A, 0,9W	7c(9mm)	Tos	2SC3468, 2SC4166, (2SC3805, 2SC4019++)
2SC2483	Si-N	TV-NF-E, 160V, 1,5A, 15W, 120MHz	13j	Tos	(2SC2238(A,B), 2SC2344, 2SC2529, ++)
2SC2484	Si-N	NF/S-L, 80V, 5A, 60W, 15MHz	18j	Mat	BD245B, 2SD718, 2SD896, 2SD1046, ++
2SC2485	Si-N	NF/S-L, 100V, 6A, 70W, 15MHz	18j	Mat	BD245C, 2SD718, 2SD896, 2SD1046, ++
2SC2486	Si-N	NF/S-L, 120V, 7A, 80W, 15MHz	18j	Mat	BD245C, 2SD718, 2SD896, 2SD1046, ++
2SC2487	Si-N	NF/S-L, 150V, 6A, 80W, 50MHz	23a	Mat	2SC2837, 2SD551, 2SD732..733, 2SD1046, ++
2SC2488	Si-N	NF/S-L, 150V, 6A, 100W, 50MHz	23a	Mat	2SC2837, 2SD551, 2SD733, 2SD1047, ++
2SC2489	Si-N	NF/S-L, 150V, 10A, 120W, 50MHz	23a	Mat	2SC2837, 2SD551, 2SD733, 2SD1047, ++
2SC249	Si-N	Uni, 70V, 0,07A, 0,5W, 170MHz	2a	Fui	BC548, 2SC2831..32, 2SC3245(A), ++
2SC2490	Si-N	UHF-L, 55V, 10A, PO=75W(770MHz)	≈57s	Fui	—
2SC2491	Si-N	hi-Ueb, hi-beta, 100V, 6A, 50W, B=800	17j	Sak	(2SC2316)
2SC2492	Si-N	NF/S-L, 120V, 10A, 100W, 70MHz	23a	Sak	2SC2837, 2SD551, 2SD733, 2SD1047, ++
2SC2493	Si-N	=2SC2492: 150V	28a		2SC2837, 2SD551, 2SD733, 2SD1047, ++
2SC2494	Si-N	UHF-Tr/E, 25V, 0,75A, PO>1,4W(500MHz)	58r	Nec	—
2SC2494M	Si-N	=2SC2494	≈58r		—
2SC2495	Si-N	UHF-L, 25V, 1,5A, PO>3,2W(500MHz)	58r	Nec	—
2SC2495M	Si-N	=2SC2495	≈58r		—
2SC2496(A)	Si-N	UHF-L, 35V, 10A, PO=37W(500MHz)	57s	Nec	BLU45/12, MRF646, MRF648, 2SC2763
2SC2497(A)	Si-N	NF/S-L, 70V, 1,5A, 5W, 150MHz	14h	Mat	BD377, BD379, 2SD794(A), 2SD1177..78++
2SC2498	Si-N	VHF/UHF, ra, 30V, 0,05A, 0,3W, 3,5GHz	7t	Tos	2SC2570(A), 2SC3037, 2SC3512
2SC2499	Si-N	VHF/UHF, ra, 20V, 0,03A, 0,3W, 4GHz	7f	Tos	2SC2570(A), 2SC3037, 2SC3512
2SC25	Si-N	Uni, 80V, 0,06A, 0,5W	2a	Mat	BC174, BC182, BC190, BC546, 2N2218++
2SC250	Si-N	RF/IF AMP, 15V, 50mA, 250MHz	2a	Fui	BF240..241, BF254..255, BF594..595, ++
2SC2500	Si-N	lo-sat, 30V, 2A, 0,9W, 150MHz	7c(9mm)	Tos	2SC3328, 2SD1146, 2SD1207, 2SD1247, ++
2SC2501	Si-N	S-L, 500/400V, 3A, 40W, 20MHz	17j	Shi	BUT93, TIP75C, 2SC2826, 2SC3038, ++
2SC2502	Si-N	S-L, 500/400V, 6A, 50W, 20MHz	17j	Shi	BUT58(A), MJE13006, 2SC2335, ++
2SC2503	Si-N	S-L, 500/400V, 6A, 80W, 20MHz	≈20j	Shi	—
2SC2504	Si-N	S-L, 500/400V, 10A, 100W, 20MHz	≈20j	Shi	—
2SC2505	Si-N	S-L, 500/400V, 3A, 60W, 20MHz	22a	Shi	BUT93, TIP75C, 2SC2826, 2SC3038, ++
2SC2508	Si-N	S-L, 500/400V, 6A, 80W, 20MHz	22a	Shi	BUT58(A), MJE13008, 2SC4108, ++

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2SC2507	Si-N	S-L, 500/400V, 20A, 200W, 20MHz	23a	Shi	BUS14(A), 2SC2930, 2SC3058, 2SC3085, ++
2SC2508	Si-N	VHF-L, 40V, 6A, PQ>27W(175MHz)	59r	Tos	MRF224
2SC2509	Si-N	AM-L, 40V, 5A, PEP=10W(28MHz)	17k(E=case)	Tos	—
2SC251(A)	Si-N	VHF/UHF, 30V, 30mA, 900MHz	5g	Nec	BF180..183, BF689, BF763, 2N2857, ++
2SC2510	Si-N	AM-L, 55V, 20A, PEP>150W(28MHz)	59r	Tos	—
2SC2511	Si-N	FM, 150MHz	7f	Hit	BF240..241, BF254..255, BF959, ++
2SC2512	Si-N	VHF-M, TV-Tuner, 30V, 50mA, 900MHz	7f	Hit	BF377..378, BF689, BF763, 2N2857, ++
2SC2516(A)	Si-N	NF/S-L, 150V, 5A, 30W, <0,5/3µs	17j	Nec	BD243D, 2SD772(A,B)
2SC2517	Si-N	=2SC2516: <500/2500ns	17j		BD243D, 2SD772(A,B)
2SC2518	Si-N	S-L, 500/400V, 5A, 40W, <1000/3200ns	17j	Nec	BUT56(A), 2SC2535, 2SC2837, 2SC3497, ++
2SC2519	Si-N	Uni, 30V, 0,03A, 0,25W, 230MHz	9b	Mat	BF240..241, BF254..255, BF594..595, ++
2SC252	Si-N	VHF/UHF, 30V, 30mA, 900MHz	5g	Nec	BF180..183, BF689, BF763, 2N2857, ++
2SC2522	Si-N	NF/S-L, 120V, 12A, 120W, 80MHz	23a	Fui	2SC2987(A), 2SD425, 2SD551, 2SD1047, ++
2SC2522A	Si-N	=2SC2522: 150V	23a		2SC2987A, 2SD733, 2SD551, 2SD1047, ++
2SC2523	Si-N	=2SC2522: 160V	23a		2SC2987A, 2SD733, 2SD551, 2SD1047, ++
2SC2524	Si-N	NF/S-L, 160V, 15A, 150W, 80MHz	23a		MJ15015, 2SC1564..65, 2SC2608, 2SD424++
2SC2525	Si-N	=2SC2522:	20j		2SC2564..2565, 2SC2788(A), 2SC2921, ++
2SC2526	Si-N	=2SC2523:	20j		2SC2565, 2SC2768(A), 2SC2921..22, ++
2SC2527	Si-N	DC-DC-Converter, 120V, 10A, 60W, 80MHz	17j	Fui	—
2SC2528	Si-N	NF/S-L, 120V, 2A, 25W, 160MHz	17j	Fui	2SC2660, 2SD759..760
2SC2529	Si-N	=2SC2528: 160V	17j		2SC2660, 2SD759..760
2SC253	Si-N	VHF/UHF, 30V, 30mA, 900MHz	5g	Nec	BF180..183, BF689, BF763, 2N2857, ++
2SC2530	Si-N	NF/S-L, 40V, 0,5A, 20W, 35MHz	17j	Fui	BD239, 2SC1398
2SC2531	Si-N	Mm, UHF-ra, 25V, 0,03A, 2,5GHz	24	Tos	BFR34, BFT97, BFW93
2SC2532	Si-N-Darl	SMD, 40V, 0,3A, B>5000	35a	Tos	BCV27
2SC2534	Si-N	S-L, 500/400V, 2A, 20W, -/<3,5µs	17j	Tos	BUV39, BUX84..85, 2SC2333, 2SC2739, ++
2SC2535	Si-N	=2SC2534: 5A, 40W	17j		BUT56(A), TIP75C, 2SC2827, 2SC3038, ++
2SC2536	Si-N	=2SC2534: 7A, 60W	18j		BU426(A), BU926, TIP56A, 2SC3040, ++
2SC2537	Si-N	S-L, 410V, 10A, 100W, -/3050ns	18j	Mit	BUV47(A), BUW12(A), 2SC2625, 2SC3042++
2SC2538	Si-N	VHF-O/Tr, 40V, 0,4A, PQ=0,6W(175MHz)	7b	Mit	BFS51, BFX55, BLW16, MRF607, ++
2SC2539	Si-N	VHF-L, 35V, 4A, PQ=17W(175MHz)	58s	Mit	—
2SC254	Si-N	Uni, 50V, 0,8A, 0,65W, 250MHz	2a	Oki	BC140..141, BC300..302, 2N3053, ++
2SC2540	Si-N	VHF-L, 35V, 10A, PQ=45W(175MHz)	57s	Mit	BLV45/12
2SC2541	Si-N	S-L, 500/450V, 10A, 100W, 16MHz	18j	Mit	BUV47(A), BUW12(A), 2SC2740, 2SC3042++
2SC2542	Si-N	S-L, 450V, 5A, 40W, <1/3µs	17j	Fjd	BUT56(A), MJE53T, 2SC2440, 2SC3056, ++
2SC2543	Si-N	Uni, 90V, 0,1A, 0,4W, 90MHz	7c	Hit	2SC2240, 2SC2363, 2SC2459, 2SC3245(A), ++
2SC2544	Si-N	=2SC2543: 120V	7c		2SC2240, 2SC2363, 2SC2459, 2SC3245(A), ++
2SC2545	Si-N	=2SC2543: ra, 60V	7c		BC414, BC550, 2SC2240, 2SC2459, ++
2SC2546	Si-N	=2SC2543: ra	7c		2SC2240, 2SC2363, 2SC2389, 2SC2459, ++
2SC2547	Si-N	=2SC2543: ra, 120V	7c		2SC2240, 2SC2363, 2SC2389, 2SC2459, ++
2SC2548	Si-N	VHF/UHF, ra, 20V, 0,03A, 0,25W, 4GHz	7f	Tos	2SC2499, 2SC2570(A), 2SC3037
2SC2549	Si-N	UHF, ra	7f	Son	BF830, 2SC2499, 2SC2570(A), 2SC2548
2SC255	Si-N	=2SC254: 60V	2a	Oki	BC140..141, BC300..301, 2N1990, ++
2SC2550	Si-N	HF/S, 60V, 0,2A, 0,3W, 250MHz	2a	Tos	BC82, BC548, 2N2221..2222(A), ++
2SC2551	Si-N	Vid, 300V, 0,1A, 0,4W, 60MHz	7c	Tos	BF299, BF393, BF420A, 2SC3468, ++
2SC2552	Si-N	S-L, 500V, 2A, 20W, -/<3,5µs	17j	Tos	BUV38, BUX84..85, 2SC2333, 2SC2738, ++
2SC2553	Si-N	=2SC2552: 5A, 40W	17j		BUT56(A), TIP75C, 2SC2827, 2SC3038, ++
2SC2555	Si-N	=2SC2552: 6A, 60W	16j		BU426(A), BU926, TIP58A, 2SC3040, ++
2SC2559	Si-N	NF/Vid-E, 130V, 1A, 200MHz	14h	Mat	2SC3117, 2SD669
2SC2558A	Si-N	=2SC2556: 160V	14h		2SC3117, 2SD669
2SC2557	Si-N	Uni, ra, 60V, 0,05A, 0,25W, 220MHz	7c	Mat	BC414, BC550, 2SC2240, 2SC2459, ++
2SC2558	Si-N	UHF-Tr/E, 35V, 0,5A, PQ=1,3W(860MHz)	58r	Nec	—
2SC2559	Si-N	UHF-L, 35V, 1,5A, PQ=6W(860MHz)	56r	Nec	2SC2885
2SC256	Si-N	=2SC254: 90V	2a	Oki	BC141, BC300..301, 2N1990, 2N2102, ++
2SC2560	Si-N	UHF-L, 35V, 3A, PQ=11W(860MHz)	56r	Nec	2SC2850
2SC2561	Si-N	Uni, HF, 30V, 0,03A, 0,25W, 250MHz	9b	Mat	BF240..241, BF254..255, BF594..595, ++
2SC2562	Si-N	lo-sat, 60V, 5A, 25W, 120MHz	17j	Tos	2SC3253..3255, 2SC3258, 2SD1235
2SC2563	Si-N	NF/S-L, 120V, 8A, 80W, 90MHz	18j	Tos	2SC2706, 2SC2837, 2SC2987(A)
2SC2564	Si-N	NF/S-L, 140V, 12A, 120W, 90MHz	20j	Tos	2SC2526, 2SC2768, 2SC2838, 2SC2921, ++
2SC2565	Si-N	=2SC2564: 160V, 15A, 150W	20j	Tos	2SC2526, 2SC2786(A), 2SC2921..2922, ++
2SC2566	Si-N	VHF, 650MHz	9b	Mat	BF314, BF502, BF505, BF507, BF959++
2SC2567	Si-N	SMD, 35V, 0,05A, 320MHz	≈35a	Mat	BC846..848, BCW31..33, BCW71..72, ++
2SC2567A	Si-N	=2SC2567: 55V	≈35a		BC846..847, BCWF569771..72, BCW81, ++
2SC2588	Si-N	Vid-L, 300V, 0,2A, 10W, 60MHz	14h	Nec	BF417, BF459, 2SC3417, 2SC3503, ++
2SC2569	Si-N	NF/S-L, 150V, 6A, 40W	22a	Fjd	BU406..408
2SC257	Si-N	=2SC254: 0,8W	2a"	Oki	→2SC254

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2SC2570(A)	Si-N	UHF, 25V, 0,07A, 5GHz	7f	Nec	2SC3037, 2SC3512
2SC2571(-1,-2)	Si-N	NF/S-L, 100..130V, 10A, 95W, 80MHz		Son	—
2SC2572	Si-N	S, 60V, 0,2A, 0,36W, <80/420ns	2a	Nec	BSV59, BSX49, 2N2221..22, 2N3903..04++
2SC2575	Si-N	Uni, 50V, 0,2A, 0,3W, 200MHz	7b	Mit	BC167, BC182, BC237, BC547, ++
2SC2575L	Si-N	=2SC2575: ra	7b		BC414, BC550, 2SC2240, 2SC2459, ++
2SC2577	Si-N	NF/S-L, 120V, 6A, 60W, 20MHz	18j	Sak	BD245C, 2SC2706, 2SC2837, 2SC2987(A), ++
2SC2578	Si-N	=2SC2577: 140V, 7A, 70W	18j		BD245D, 2SC2706, 2SC2987(A), 2SD1047, ++
2SC2579	Si-N	=2SC2577: 160V, 8A, 80W	18j		BD245D, 2SC1067A, 2SC3263..3264, 2SD1040
2SC258	Si-N	=2SC255: 0,8W	2a°	Oki	→2SC255
2SC2580	Si-N	=2SC2577: 180V, 9A, 90W	18j		BD245E, 2SC3263..3264, 2SD751
2SC2581	Si-N	=2SC2577: 200V, 10A, 100W	18j		BD245F, 2SC3263..3264
2SC2582	Si-N	NF/HF/S-L, 45V, 1A, 10W, 200MHz	14h	Mat	BD135, BD225, BD375, 2SD1378, ++
2SC2564	Si-N	VHF-L, 45V, 4A, PQ=22W(175MHz)	58r	Nec	2SC2094
2SC2585	Si-N	UHF, ra, 24V, 0,4W, 0,065A, 8,5GHz	51s	Nec	BFG195, BFQ82, 2SC3358, 2SC3603
2SC2586	Si-N	UHF-Tr/E, 35V, 0,4A, PQ=1,6W(500MHz)	2e(E=case)	Nec	(BFS50, MRF629, 2SC2762, 2SC3185, ++)
2SC2567(A)	Si-N	NF/S-L, 150V, 10A, 120W, 70MHz	20j	Nec	2SC2525, 2SC2585, 2SC2838, 2SD745A,B, ++
2SC2588(A)	Si-N	NF/S-L, 150V, 12A, 120W, 60MHz	20j	Nec	2SC2526, 2SC2564..2585, 2SC2838, ++
2SC2589	Si-N	NF/S-L, 160V, 10A, 200W, 60MHz	23a	Nec	BDW16, 2SC1585..86, 2SC2607..06, ++
2SC259	Si-N	=2SC258: 0,8W	2a°	Oki	→2SC258
2SC2590	Si-N	NF/S-L, 120V, 0,5A, 5W, 200MHz	14h	Mat	2SC2690(A), 2SD1382, 2SD1563
2SC2591	Si-N	NF/S-L, 150/150V, 1A, 20W, 200MHz	17j	Mat	2SC1913(A), 2SC2238(A,B), 2SC2344, ++
2SC2592	Si-N	=2SC2591: 180/160V	17j		2SC1913A, 2SC2238A,B, 2SC2344, 2SC2660
2SC2593	Si-N	Sym, 20/20/20V, 0,05A, 0,14W	7c	Son	—
2SC2594	Si-N	NF/S-L, 40V, 5A, 10W, 150MHz	14h	Mat	MJE200, 2SC3420, 2SD741, 2SD828, ++
2SC2595	Si-N	UHF-L, 38V, 1,2A(ss), PQ=0,9W(840MHz)	51r	Mat	—
2SC2598	Si-N	UHF-L, 36V, 4A(ss), PQ=3,5W(640MHz)	51r	Mat	—
2SC2597	Si-N	UHF-L, 38V, 6A(ss), PQ=9W(840MHz)	51r	Mat	—
2SC2598	Si-N	Dual, UHF, 20V, 0,07A, 5GHz		Fui	—
2SC2599	Si-N	UHF, ra, 20V, 0,02A, 0,2W	52r	Fui	BFG90, BFQ28, BFQ60, BFQ71, BFR49
2SC26	Si-N	Uni, 60V, 0,1A, 0,5W, 150MHz	37a	Fui	BC174, BC182, BC190, BC546, 2N2219++
2SC260	Si-N	HF-L, 30V, 1A, 260MHz	2a	Oki	(BD135, BD226, 2SC3419, 2SD1200, ++)
2SC2600	Si-N	UHF, 25V, 0,04A, 0,35W, 8GHz	52r	Fui	BFQ57..58, BFQ74, 2SC1655..1658, ++
2SC2801	Si-N	Dual, 70V, 0,2A, 0,4W, 100MHz	7-SIP	Mit	—
2SC2602	Si-N	Uni, ra, MC-Cartridge, 70V, 0,2A, 0,5W	7b	Mit	2SC2240, 2SC2459, 2SC2574..2875, ++
2SC2603	Si-N	Uni, 50V, 0,2A, 0,3W, 200MHz	41c	Mit	BC167, BC182, BC237, BC547, ++
2SC2604	Si-N	Uni, ra, 30V, 0,1A, 0,2W, 230MHz	7c	Hit	BC169, BC164, BC239, SC549, ++
2SC2605	Si-N	=2SC2604: 50V	7c		BC164, BC413..414, BC550, 2SC2240, ++
2SC2606	Si-N	Vid-L, 300V, 0,05A, 30MHz	≈17j	Son	2SC1505..1507, 2SC1755..1757, 2SC1905, ++
2SC2607	Si-N	S-L, 200V, 15A, 150W, 20MHz	23a	Sak	MJ15015, BDW18, 2SD665, 2SD753, ++
2SC2S06	Si-N	=2SC2607: 17A, 200W	23a		BUV11, BUW56, BUX11, 2SC2865(A)
2SC2609	Si-N	VHF-L, 55V, 15A, PQ=110W(220MHz)	57s	Mit	2SC2897
2SC261	Si-N	=2SC260: 60V	2a	Oki	(BD137, BD228, 2SD1200, 2SD1378, ++)
2SC2610	Si-N	Vid, 300V, 0,1A, 0,6W, 60MHz	7c(9mm)	Hit	BF299, BF393, BF420A, 2SC3468..69, ++
2SC2611	Si-N	=2SC2610:	14h		BF417, BF458, 2SC3417, 2SC3503, ++
2SC2812	Si-N	S-L, 500/400V, 3A, 30W	17j	Hit	BUT93, TIP75C, 2SC2826, 2SC3038, ++
2SC2613(K)	Si-N	=2SC2612: 5A, 40W	17j		BUT58(A), 2SC2535, 2SC2827, 2SC3497, ++
2SC2814	Si-N	=2SC2612: 5A, 60W	20j		—
2SC2515	Si-N	=2SC2612: 6A, 60W	20j		2SC2650, 2SC2618
2SC2816	Si-N	=2SC2612: 10A, 100W	23a		BUW25..28, BUW34..38, 2SC3043, ++
2SC2617	Si-N	=2SC2612: 15A, 125W	23a		BUV25, BUW44, BUX25, 2SD841, ++
2SC2816	Si-N	SMD, Uni, 35V, 0,5A, 50MHz	35a	Hit	BC617, BCX19, 2SC3325, 2SC3341, ++
2SC2819	Si-N	SMD, Uni, 30V, 0,1A, 230MHz	35a	Hit	BC846..848, BCW31..33, BCW71..72, ++
2SC282	Si-N	=2SC260: 80V	2a	Oki	(BD139, BD230, 2SD1200, 2SD1376, ++)
2SC2620	Si-N	SMD, VHF, 30V, 0,02A, 940MHz	35a	Hit	BFS17, 2SC3005, 2SC3016, 2SC3161
2SC2621	Si-N	Vid, 300V, 0,2A, 10W, >50MHz	14h	Ful, Say	BF417, BF459, MJE3440, 2SC3503, ++
2SC2823	Si-N	S-L, 450V, 20A, 100W, <1/4µs	23a	Fjd	BUV24, BUX24, 2SC3085
2SC2624	Si-N	S-L, 450V, 5A, 60W, <1/3µs	18j	Fjd	BU426(A), TIP57A..58A, 2SC3063, ++
2SC2625	Si-N	=2SC2624: 10A	18j		BUW12(A), 2SC2541, 2SC2740, 2SC2789, ++
2SC2828	Si-N	=2SC2624: 400V, 15A, <0,8/2,8µs	18j		BUW13(A), 2SC2307, 2SC3520, 2SC3451, ++
2SC2627	Si-N	VHF-L, 35V, 2A, PQ=6W(175MHz)	≈55s	Mit	BLW16, BLY82, 2SC2261
2SC2628	Si-N	VHF-L, 35V, 4A, PQ=16W(175MHz)	≈55s	Mit	BLY89, MRF209, 2N5591, 2N6082, ++
2SC2828	Si-N	VHF-L, 35V, 6A, PQ=34W(175MHz)	≈55s	Mit	2N6084
2SC263	Si-N	Min, HF/S, 15V, 0,12A, 0,1W, 200MHz	24c	Oki	(BSX27, BSX92..93, 2N2368..69(A), ++)
2SC2830	Si-N	VHF-L, 35V, 14A, PQ=60W(175MHz)	57s	Mit	BLV75/12, 2SC3147
2SC2831	Si-N	Uni, ra, 150V, 0,05A, 0,75W, 160MHz	7c	Mat	2SC3800
2SC2832	Si-N	=2SC2831: 1W	7c(9mm)		2SC3800

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2SC2633	Si-N	=2SC2631:	17j		—
2SC2634	Si-N	Uni, ra, 60V, 0,1A, 0,4W, 200MHz	7c	Mat	BC550, 2SC2240, 2SC2389..90, 2SC2459, ++
2SC2635	Si-N	S, 650V, 0,1A, 0,75W, 15MHz	2a	Hit	2N5012..15, 2SC1762, 2SD594
2SC2636	Si-N	UHF, 30V, 0,05A, 0,4W, 1200MHz	9c	Mat	BF357, BF377..378, 2SC2570(A), 2SC3037
2SC2637	Si-N	Vid-E, 300/300V, 0,1A, 15W, 100MHz	13j	Mat	(BF617, BF758..759, MPS-U10, ++)
2SC2638	Si-N	VHF-L, 35V, 2A, PQ>6W(175MHz)	58s	Tos	—
2SC2639	Si-N	VHF-L, 35V, 3,5A, PQ>15W(175MHz)	58s	Tos	2SC2094
2SC264	Si-N	=2SC263: 30V, 400MHz, 27/40ns	24c	Oki	(BSX92..93, 2N2368..89(A), 2N3011, ++)
2SC2640	Si-N	VHF-L, 35V, 6A, PQ>26W(175MHz)	58s	Tos	—
2SC2641	Si-N	UHF-L, 35V, 1,4A, PQ>6W(470MHz)	58s	Tos	MRF641, 2SC2284
2SC2642	Si-N	UHF-L, 35V, 2,8A, PQ>12W(470MHz)	58s	Tos	—
2SC2643	Si-N	UHF-L, 35V, 6A, PQ>25W(470MHz)	58s	Tos	—
2SC2644	Si-N	UHF, 25V, 0,12A, 0,5W, 4GHz	7l	Tos	2SC3337
2SC2645	Si-N	VHF/UHF, 30V, 0,05A, 0,2W, 1200MHz	24b	Mat	BF362, BF363
2SC2646	Si-N	VHF/UHF, 30V, 0,05A, 0,2W, 1200MHz	9b	Mat	BF377..378, BF689, BF763, 2N2857, ++
2SC2647	Si-N	AM/FM, 30V, 0,03A, 0,4W, 230MHz	9c	Mat	BF240..241, BF254..255, BF594..595, ++
2SC2648	Si-N	UHF-L, 35V, 3,5A, PQ=17W(470MHz)	55r	Tos	BLX69, 2SC1404
2SC2649	Si-N	UHF-L, 35V, 6A, PQ=22W(470MHz)	55r	Tos	2SC1339, 2SC2173
2SC265	Si-N	=2SC263: 40V	24c	Oki	(BSS11, BSX92..93, 2N2368..69(A), ++)
2SC2650	Si-N	S-L, 500V, 10A, 100W, -/<3,5µs	20j	Tos	2SC2818
2SC2651	Si-N	AM-L, 45V, 25A, PEP=90W(28MHz)	59r	Tos	2SC2679
2SC2652	Si-N	AM-L, 85V, 20A, PEP=220W(28MHz)	59r	Tos	—
2SC2653	Si-N	Vid-L, TV-VA, 350V, 0,2A, 15W, >50MHz	13j	Mat	BF759
2SC2653(H)	Si-N	=2SC2653: 400/300V	13j	Mat	—
2SC2654	Si-N	NF/S-L, 40V, 7A, 40W, <1/3,5µs	17j	Nec	BD243, BD543, BD795, 2SD613, ++
2SC2655	Si-N	NF/S, 60V, 2A, 0,9W, 100MHz	7c(9mm)	Tos	2SC3328, 2SC3669, 2SD1207, 2SD2177, ++
2SC2656	Si-N	S-L, 450V, 7A, 60W, <1,5/4,5µs	18j	Fjd	BU426(A), TIP57A..58A, 2SC2788, ++
2SC2657	Si-N	S-L, 800/500V, 1,5A, 70W, 2,5MHz	23a	Mat	BU426(A), BUW11(A), BUX46(A), 2SC3091
2SC2657A	Si-N	=2SC2657: 900/500V	23a		BU426A, BUW11A, BUX46A, 2SC3155, ++
2SC2658	Si-N	S-L, 800/500V, 5A, 90W, 3MHz	23a	Mat	BU426(A), BUW11(A), BUX46(A), BUX82
2SC2658A	Si-N	=2SC2659: 900/500V	23a		BU426A, BUW11A, BUX46A, BUX63, ++
2SC2659	Si-N	S-L, 800/500V, 7A, 120W, 3,5MHz	23a	Mat	BU546, BUS12(A), BUW35..36, BUX81, ++
2SC2659A	Si-N	=2SC2659: 900/500V	23a		BU546, BUS12A, BUW36, BUX81, ++
2SC266	Si-N	NF/HF, 30V, 0,03A, 0,1W, 250MHz	24b	Nec	BC188, BC183, BC236, BC546, 2SD767++
2SC2660(A)	Si-N	NF/S-L, TV-VA, 200V, 2A, 30W, 30MHz	17j	Mat	2SD386..367(A), 2SD760, 2SD1136
2SC2662	Si-N	NF/HF/S, 100V, 3A, 8W(Tc=25°), 50MHz	2a	Tos	BSX64, 2N4239, 2SC696(A), 2SC2214, ++
2SC2664	Si-N	S-L, 100V, 3A, 10W, 50MHz	43a	Tos	(BD791, BDX35..37, MJE243..244, ++)
2SC2665	Si-N	NF/S-L, 100V, 4A, 55W, 10MHz	16j	Sak	BD245C, BDV95, 2SD718, 2SD895..896, ++
2SC2666	Si-N	VHF-L35V, 3,5A, PQ=7W(270MHz)	55r	Tos	BLW15, BLW81, 2SC2106
2SC2667	Si-N	VHF-L35V, 6A, PQ=20W(270MHz)	55r	Tos	2SC2173
2SC2668	Si-N	FM-V, 40V, 20mA, 0,1W, 550MHz	41c	Tos	BF255, BF314, BF495, BF502, BF595++
2SC2669	Si-N	AM/FM-ZF, 35V, 50mA, 0,2W, >100MHz	41c	Tos	BF240, BF254, BF494, BF594, ++
2SC267	Si-N	NF-E, 35V, 0,2A, 0,15W, 90MHz	24b	Nec	BC188, BC163, BC236, BC546, 2SD767++
2SC2670	Si-N	HF, AM, ra, 35V, 0,1A, 0,2W, >60MHz	41c	Tos	BF240..241, BF254..255, BF594..595, ++
2SC2671(F)(H)	Si-N	UHF, 25V, 70..80mA, ≈5GHz	7l	Mat	2SC2570(A), 2SC3037, 2SC3337
2SC2672	Si-N	UHF, 30V, 0,05A, 0,25W, 3GHz	51s	Nec	BFQ72
2SC2673	Si-N	NF-Tr/E, 40V, 1A, 0,6W, 150MHz	9c	Rhm	BC337, BC635, 2SD1225, 2SD1616, ++
2SC2674	Si-N	=2SC2675: 120V	7c	Rhm	2SC2240, 2SC2459
2SC2675	Si-N	NF, ra, MM-/MC-Catridge, 60V, 0,1A	7c	Rhm	2SC2240, 2SC2459, 2SC2602
2SC2676(1)	Si-N	NF, ra, 60V, 0,01A, 0,6W, 200MHz	9b	Nec	2SC1775(A), 2SC2240, 2SC2369..2390, ++
2SC2677	Si-N	Uni, 30V, 0,1A, 0,625W, 230MHz	7a	Hit	BC236, BC546, BF240..41, BF254..55++
2SC2678	Si-N	Uni, 20V, 0,03A, 0,5W, 300MHz	7e	Hit	BC236, BC548, BF240..41, BF254..55++
2SC2679	Si-N	UHF-O, 30V, 0,05A, PQ=8mW(930MHz)	7e	Hit	BF357, BF377..378, 2SC2570(A), 2SC3037
2SC267A	Si-N	=2SC267: 50V	24b		BC187, BC162, BC237, BC547, 2SD787++
2SC268	Si-N	Nix, S, 60V, 0,03A, 0,15W, 150MHz	24b	Nec	BC174, BC182, BC190, BC546, 2SD767++
2SC2680	Si-N	SMD, TV-ZF, 550MHz	35a	Mat	BF599, BF799, 2SC3053, 2SC3374, ++
2SC2681	Si-N	NF/HF-L, 115V, 10A, 100W, 60MHz	16j	Nec	2SC2706, 2SC2637, 2SC2987, (BD245C, ++)
2SC2682	Si-N	NF-Tr-L, 180V, 0,1A, 8W, 200MHz	14h	Nec	BF415, BF417, BF458..459, 2SC3416, ++
2SC2684	Si-N	UHF-A/Tr, 36V, 0,6A, PQ=0,95W(940MHz)	51r	Mat	—
2SC2685	Si-N	UHF-A/Tr, 36V, 2A, PQ=5,5W(940MHz)	58v	Mat	—
2SC2686	Si-N	UHF-L, 36V, 3A, PQ=13W(940MHz)	58v	Mat	—
2SC2687	Si-N	NF/Vd, 300V, 0,2A, 0,8W, 80MHz	9b	Nec	BF299, BF420A, BF393, 2SC3468, ++
2SC2688	Si-N	Vid-L, 300V, 0,2A, 10W, 80MHz	14h	Nec	BF417, BF459, 2SC3417, 2SC3503
2SC2689	Si-N	NF/Vid-L, 300V, 0,2A, 10W, 80MHz	13j	Nec	(BF362, BF617, BF859, MPS-U10, ++)
2SC268A	Si-N	=2SC268: 90V	24b		BC546, BF297..299, BF422, BSS36, ++
2SC268B	Si-N	=2SC268: 150V	24b		BF297..299, BF422, BFR87, 2SC3467, ++

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2SC269	Si-N	S, 25V, 0,2A, 0,15W, 400MHz, 14/25ns	24b	Nec	BSS11..12, BSX19..20, 2N2368..69(A),++
2SC2690	Si-N	NF/HF-L, 120V, 1,2A, 20W, 155MHz	14h	Nec	2SC3117, 2SD669
2SC2690A	Si-N	=2SC2690: 160V	14h		2SC3117, 2SD669
2SC2691	Si-N	Uni, 20V, 0,05A, 0,2W, 100MHz	7b	Mit	BC168, BC183, BC238, BC548,++
2SC2692	Si-N	UHF-Tr/E, 28V, 0,2A, PQ=0,45W(2GHz)	≈55s	Nec	BFQ68, BFT98
2SC2693	Si-N	AM-L, 70V, 5A, PEP=12W(28MHz)	59r	Tos	—
2SC2694	Si-N	VHF-L, 35V, 20A, PQ=75W(175MHz)	57s	Mit	MRF244, 2SC2782
2SC2695	Si-N	UHF-L, 35V, 10A, PQ=32W(520MHz)	58s	Mit	—
2SC27	Si-N	HF, 60V, 0,1A, 0,65W, 350MHz	2a	Fui	BFW16..17, BFX55, 2N3725, 2SC1385,++
2SC270	Si-N	S-L, 270V, 5A, 50W, 22MHz	23a	Son	BU606..606, BUX16A..C, 2SD1154,++
2SC2700	Si-N	UHF-L, 45V, 1A, PQ=6,5W(470MHz)	55r	Fui	BLX93, 2SC1040
2SC2701	Si-N	UHF-Tr/E, 35V, 0,3A, PQ=1,1W(2,3GHz)	62d	Fui	—
2SC2702	Si-N	UHF-Tr/E, 35V, 0,5A, PQ=2,2W(2,3GHz)	62d	Fui	—
2SC2703	Si-N	Uni, 30V, 1A, 0,9W, 150MHz	7c(9mm)	Tos	2SC2236, 2SD863, 2SD1207, 2SD1331,++
2SC2704	Si-N	NF-L, 150V, 0,05A, 10W, 200MHz	14h	Tos	BF415, BF417, BF457..459, 2SC3502,++
2SC2705	Si-N	=2SC2704: 0,8W	7c(9mm)	Tos	BF297..299, BF422(A), 2SC3467..69,++
2SC2706	Si-N	NF/HF/S-L, 140V, 10A, 100W, 90MHz	18j	Tos	2SC2837
2SC2707	Si-N	NF/S-L, 180V, 15A, 150W, 80MHz	23a	Tos	MJ15015, BDW16, 2SC2607..08, 2SD753,++
2SC271	Si-N	UHF, 25V, 20mA, 1100MHz	24b	Nec	BF362..363
2SC2710	Si-N	Uni, 35V, 0,8A, 0,3W, 120MHz	41c	Tos	BC337..338, BC635, BC637, BC639,++
2SC2711	Si-N	VHF-L, 35V, 0,8A, PQ=6W(175MHz)	51r	Tos	—
2SC2712	Si-N	SMD, Uni, 60V, 0,15A, 150MHz	35a	Tos	BC846, BCV71..72, 2SC3323, 2SC3340,++
2SC2713	Si-N	SMD, Uni, ra, 120V, 0,1A, 100MHz	35a	Tos	2SC3324
2SC2714	Si-N	SMD, HF, 40V, 0,02A, 550MHz	35a	Tos	BF599, BF799, BFS20, 2SC3015,++
2SC2715	Si-N	SMD, HF, 35V, 0,05A, >100MHz	35a	Tos	BF554, BFS18..19, BF840..841
2SC2716	Si-N	SMD, HF/NF, 35V, 0,1A, 120MHz	35a	Tos	BC846..848, BCW31..33, BF554,++
2SC2717	Si-N	TV-ZF-E, >300MHz	71	Tos	BF198..199, BF224..225, BF596..597,++
2SC2718	Si-N	Uni, 60V, 0,1A, 0,25W, 250MHz	7c	Nec	BC174, BC182, BC190, BC546,++
2SC2719	Si-N	HF/S, 80V, 0,3A, 0,6W, 50/560ns	7c	Nec	BC639, BSW63..64, 2N2221A..2222A,++
2SC272	Si-N	UHF, 25V, 20mA, 1200MHz	24b	Nec	BF362..363
2SC2720	Si-N	NF/S, 60V, 0,5A, 0,6W, <35/275ns	7e	Nec	BSV59, BSX49, 2N2221..2222(A),++
2SC2721	Si-N	Uni, 60V, 0,7A, 1W, 110MHz	9b	Nec	BC637, BC639, 2N2221..2222(A),++
2SC2722	Si-N	NF/S-L, 100V, 15A, 150W, 20MHz	20j	Sak	2SC2525..2526, 2SC2564..2565, 2SC2838,++
2SC2723	Si-N	S-L, 450V, 15A, 150W, 30MHz	18j	Sak	BUV46(A..C), BUW13(A), 2SC3520,++
2SC2724	Si-N	FM-ZF, 30V, 30mA, 200MHz	41c	Mit	BF240..241, BF254..255, BF594..595,++
2SC2725	Si-N	Dual, 100V, 0,1A, 0,4W, 100MHz	7-SIP	Mit	—
2SC2726	Si-N	UHF, 15V, 0,02A, 0,2W, 1100MHz	25p	Hit	2SC2464, 2SC2466, 2SC2144, 2SC2360,++
2SC2727	Si-N	VHF, TV-Tuner, 15V, 0,02A, >700MHz	25q	Hit	2SC2454, 2SC2464, 2SC2466, 2SC2144,++
2SC2728	Si-N	UHF, 15V, 0,02A, 0,2W, 2500MHz	25p	Hit	2SC2466, 2SC2353
2SC2729	Si-N	VHF, 15V, 0,05A, 0,2W, 1300MHz	25q	Hit	2SC2454
2SC273	Si-N	Uni, 120V, 0,05A, 0,5W, 150MHz	2a	Nec	BF257..259, 2SC3245(A), 2SC3248,++
2SC2730	Si-N	UHF-O, 15V, 0,05A, 0,2W, 1600MHz	24b	Hit	BF362..363
2SC2731	Si-N	UHF-O, 20V, 0,05A, 0,2W, 3500MHz	25p	Hit	BFQ59, BFQ70, 2SC2143, 2SC2844,++
2SC2732	Si-N	SMD, UHF, 30V, 0,02A, 1000MHz	35a	Hit	BFS17, 2SC3005, 2SC3016, 2SC3161
2SC2733	Si-N	SMD, VHF, 30V, 0,05A, 1000MHz	35a	Hit	BFS17, 2SC3005, 2SC3016, 2SC3161
2SC2734	Si-N	SMD, UHF, 20V, 0,05A, 3500MHz	35a	Hit	BFT75, 2SC3014
2SC2735	Si-N	SMD, VHF/UHF-O, 30V, 0,05A, 1200MHz	35a	Hit	BFS17, 2SC3005, 2SC3016, 2SC3161
2SC2736	Si-N	SMD, VHF/UHF, 30V, 0,05A, 2200MHz	35a	Hit	BFR53, BFT75, 2SC3014
2SC2737	Si-N	UHF, ra, 20V, 0,06A, 8GHz	71	Nec	—
2SC2738	Si-N	S-L, 500/400V, 2A, 25W, 11MHz	17j	Mat	BUX84..85, 2SC2333, 2SC2534, 2SC3169,++
2SC2739	Si-N	S-L, 500/400V, 7A, 40W, 11MHz	17j	Mat	BUT56(A), 2SC2427, 2SC3039, 2SC3170,++
2SC274..279	Si-N			Oki	—
2SC2740	Si-N	S-L, 500/400V, 10A, 100W, 11MHz	18j	Mat	BUW12(A), 2SC2789, 2SC2828, 2SC3042,++
2SC2741	Si-N	VHF-Tr/E, 38V, 1A, PQ=2,5W(175MHz)		Fui	—
2SC2743	Si-N	VHF-L, 38V, 5A, PQ=15W(175MHz)	61s	Fui	—
2SC2744	Si-N	UHF-Tr/E, 38V, 1A, PQ=2,5W(470MHz)		Fui	—
2SC2745	Si-N	UHF-L, 36V, 4A, PQ=9W(470MHz)	61r	Fui	—
2SC2746	Si-N	UHF-L, 38V, 5A, PQ=15W(470MHz)	61s	Fui	—
2SC2748	Si-N	Dual, 30V, 0,03A, 0,4W, 200MHz	5-SIP	Mit	—
2SC2749(A)	Si-N	S-L, 500V, 10A, 100W, <1/3,2µs	16j	Nec	BUW12(A), 2SC3042, 2SC3435, 2SC4138,++
2SC2750	Si-N	S-L, 150V, 15A, 100W, <1/1,8µs	16j	Nec	2SC2944, 2SC2987A, 2SD1047
2SC2751(A)	Si-N	S-L, 500V, 15A, 120W, <1/3,2µs	16j	Nec	BUW13(A), 2SC3435, 2SC3520, 2SC4140,++
2SC2752	Si-N	S-L, 500/400V, 0,5A, 10W, <1/3,5µs	14h	Nec	BD410, 2SC2899, 2SC3051, 2SC3425
2SC2753	Si-N	UHF, 17V, 0,07A, 0,3W, 5GHz	71	Tos	2SC2570(A), 2SC3037
2SC2754	Si-N	S, 35V, 0,1A, 0,1W, 400MHz, 30/470ns	7c	Tos	BSW41, BSY63, 2N708, 2N4123..24,++
2SC2755	Si-N	SMD, VHF, 30V, 0,02A, 600MHz	35a	Nec	BF599, BF799, BFS20, 2SC3015,++

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2SC2756	Si-N	SMD, VHF-M, 20V, 0,02A, 850MHz	35a	Nec	BF599, BF799, BFS20, 2SC3015, ++
2SC2757	Si-N	SMD, VHF/UHF-M/O, 30V, 0,05A, 1100MHz	35a	Nec	BFS17, 2SC3005, 2SC3016, 2SC3181
2SC2758	Si-N	SMD, UHF-V, ra, 30V, 0,02A, 1000MHz	35a	Nec	BFS17, 2SC3161
2SC2759	Si-N	SMD, VHF/UHF-M/O, 30V, 0,05A, 2000MHz	35a	Nec	BFS17, 2SC3005, 2SC3016, 2SC3161
2SC2760	Si-N	UHF-L, 50V, 10A, PQ=34W(470MHz)	≈57s	Fui	2N6439, 2SC2796, 2SC2895
2SC2761	Si-N	S-L, 450/400V, 30A, 200W	23a	Sak	BUS14(A), BUS96(A), C2930, C3058
2SC2762	Si-N	UHF-Tr/E, 35V, 0,4A, PQ=1,4W(500MHz)	2a	Nec	BFS50, MRF629, 2SC2852, 2SC3185
2SC2763	Si-N	UHF-L, 35V, 4A, PQ=16W(500MHz)	58r	Nec	2SC1968
2SC2766	Si-N	NF/S-L, 160V, 15A, 150W, 60MHz	20j	Nec	2SC2526, 2SC2565, 2SC2921, 2922, ++
2SC2766A	Si-N	=2SC2766: 160V	20j		2SC2773..2774, 2SC2922, 2SC3370, ++
2SC2767	Si-N	S-L, 250V, 5A, 40W, <1/3µs	17j	Fjd	BU406..409, MJE51T..53T, 2SC3058, ++
2SC2768(A)	Si-N	S-L, 250V, 7A, 40W, <1/3µs	17j	Fjd	BU406..409, TIP150..162, 2SC2427, ++
2SC2769	Si-N	S-L, 250V, 10A, 100W, <0,8/2,5µs	18j	Fjd	BU124(A), TIP160..162, 2SC2961, ++
2SC2770	Si-N	S-L, 600V, 100A, 770W, <4/11µs		Fjd	—
2SC2771	Si-N	Dual, 60V, 0,1A, 0,5W, 140MHz	7-SIP	Mit	—
2SC2773	Si-N	S-L, 200/200V, 15A, 150W, 20MHz	20j	Sak	2SC3370, 2SC3264, 2SD846
2SC2774	Si-N	S-L, 200/200V, 17A, 200W, 20MHz	20j	Sak	2SC3264
2SC2775	Si-N	SMD, Uni, 90V, 0,05A, 200MHz	35a	Hit	2SC1622A, 2SC3324, 2SC3340
2SC2776	Si-N	SMD, FM/VHF, 320MHz	35a	Hit	BF599, BF799, BFS20, 2SC3015, ++
2SC2778	Si-N	SMD, AM/FM, 30V, 0,03A, 230MHz	35a	Mat	BF554, BF599, BF799, BFS18..20, ++
2SC2760	Si-N	SMD, Uni, 140V, 0,05A, 120MHz	39b	Nec	2SC2880, 2SD1009, 2SD1464
2SC2781	Si-N	UHF-OTr/E, 35V, 0,5A, PQ=0,9W(2,3GHz)	62c	Fui	—
2SC2762	Si-N	VHF-L, 36V, 20A, PQ=90W(175MHz)	57r	Tos	—
2SC2763	Si-N	UHF-L, 36V, 8A, PQ=45W(470MHz)	57r	Tos	BLV45/12
2SC2784	Si-N	Uni, ra, 120V, 0,05A, 0,3W, 110MHz	40c	Nec	2SC1775(A), 2SC2240, 2SC2459, 2SC3378, ++
2SC2785	Si-N	Uni, 60V, 0,1A, 0,25W, 250MHz	40c	Nec	BC174, BC162, BC190, BC546, ++
2SC2786	Si-N	FM, 30V, 20mA, 600MHz	40c	Nec	BF225, BF314, BF502, BF505, BF507++
2SC2787	Si-N	AM, 50V, 30mA, 250MHz	40c	Nec	BF240..241, BF254..255, BF594..595, ++
2SC2766	Si-N	S-L, 500/400V, 8A, 80W, 20MHz	18j	Shi	BU928, TIP58A, 2SC2536, 2SC3040, ++
2SC2769	Si-N	S-L, 500/400V, 10A, 100W	18j	Shi	BUV47(A), BUW12(A), 2SC2828, 2SC3042++
2SC2790(A)	Si-N	S-L, 850/800V, 2A, 80W, <1/5µs	23a	Tos	BU326A, BU426A, BUW11(A), BUX46(A)++
2SC2791	Si-N	S-L, 900V, 5A, 100W, <1/4,5µs	23a	Tos	BU426A, BUS11A, BUW11A, BUX46A, ++
2SC2792	Si-N	S-L, 850/800V, 2A, 80W, <1/5µs	18j	Tos	BU426A, BUW11(A), 2SC3151..3152, ++
2SC2793	Si-N	S-L, 900/800V, 5A, 100W, <1/4,5µs	20j	Tos	2SC2980
2SC2794	Si-N	NF/S-L, 60V, 2A, 25W, 40MHz	14h	Tos	BD177, BD235, BD377, 2SD794(A), ++
2SC2796	Si-N	UHF-L, 45V, 8A, PQ=44W(470MHz)	57s	Mit	2N6439, 2SC2895
2SC2797	Si-N	UHF-L, 45V, 1A, PQ=6W(770MHz)	≈55a	Mit	—
2SC2798	Si-N	UHF-L, 45V, 2A, PQ=14W(770MHz)	≈55a	Mit	—
2SC2799	Si-N	UHF-L, 45V, 4A, PQ=27W(770MHz)	≈55s	Mit	—
2SC28	Si-N	Uni, 40V, 0,05A, 0,225W, 100MHz	2a	Fui	BC187, BC182, BC237, BC547, 2N2218++
2SC280(H)	Si-N	DuaL, 30V, 0,01A, 0,08W		Hit	—
2SC2800	Si-N	UHF-L, 45V, 6A, PQ=42W(770MHz)	57s	Mit	—
2SC2802	Si-N	NF/Vid-E, 300V, 0,2A, 10W, 80MHz	30j	Nec	(BF417, BF817, BF758..759, MPS-U10++)
2SC2603	Si-N	NF/HF/S-L, 150V, 1A, 20W, 200MHz	14h	Mat	2SC2890A, 2SC3117, 2SD669
2SC2S04	Si-N	UHF, 25V, 0,02A, 0,2W, 900MHz	25p	Tos	2SC2464, 2SC2466, 2SC2144, 2SC2360, ++
2SC2S05	Si-N	UHF, 30V, 0,05A, 0,2W, 1500MHz	25(B-EC)	Tos	2SC2464, 2SC2488, 2SC2144, 2SC2360, ++
2SC2806	Si-N	VHF, 30V, 0,05A, 0,2W, 1100MHz	25(B-EC)	Tos	2SC2464, 2SC2466, 2SC2144, 2SC2360, ++
2SC2608(S)	Si-N	Uni, 160V, 0,05A, 0,5W, 140MHz	7c, 41c	Rhm	BF297..299, BF422, 2SC3248, 2SC3467, ++
2SC2S09	Si-N	S-L, 300V, 2A, 50W, 20MHz	18j	Sak	BUW11(A), TIP51..54, 2SC2824, ++
2SC281(H)	Si-N	Uni, 30V, 0,1A, 0,2W, >80MHz	2a	Hit	BC166, BC163, BC235, BC548, 2SD787++
2SC2810	Si-N	S-L, 500/400V, 7A, 50W, 18MHz	17j	Sak	BUT58(A), MJE13006, 2SC4055, 2SC4106, ++
2SC2811	Si-N	UHF-Tr/E, 45V, 1A, PQ=1,4W(950MHz)		Nec	—
2SC2812	Si-N	SMD, Uni, 55V, 0,15A, 100MHz	35a	Say	BC846..647, BCW71..72, BCW81, ++
2SC2813	Si-N	SMD, VHF, 25V, 0,03A, 600MHz	35a	Say	BF599, BF799, BFS20, 2SC3015, ++
2SC2814	Si-N	SMD, HF, 30V, 0,03A, 320MHz	35a	Say	BF554, BFS18..20, BF599, BF799, ++
2SC2S15	Si-N	S-L, 300/250V, 5A, 40W, <0,5/2µs	17j	Hit	BU406..406, MJE51T..53T, 2SC2907, ++
2SC2816	Si-N	S-L, 500/400V, 5A, 40W, <0,5/2µs	17j	Hit	BUT52, BUT58(A), 2SC4106, 2SC3497, ++
2SC2817	Si-N	S-L, 300/250V, 10A, 80W, <0,5/2µs	20j	Hit	2SC2850
2SC2818	Si-N	S-L, 500/400V, 10A, 100W, <0,5/2µs	23a	Hit	BUW25, BUW34..35, 2SC3046, 2SC4136, ++
2SC2S19	Si-N	S-L, 500/400V, 15A, 100W, <0,5/2µs	23a	Hit	BUV25, BUW44, BUX25, 2SD641, ++
2SC2S2(H)	Si-N	=2SC2S1: 0,35W	2a	Hit	BC186, BC163, BC236, BC548, 2SD787++
2SC2820	Si-N	S-L, 500/400V, 20A, 125W, <1/3,5µs	23a	Hit	2SC3085, 2SC3094, 2SC3593
2SC2821	Si-N	SMD, Uni, 20V, 0,05A, 230MHz	35a	Hit	BC646..848, BCW31..33, BCW71..72, ++
2SC2822	Si-N	S, 75V, 0,8A, 0,36W, <35/300ns	2a	Nec	BSW83..64, 2N2221A..2222A
2SC2S23	Si-N-Darl	NF/S-L, 120V, 7A, 70W, B=15000	18j	Tos	BDV65C, 2SD1123, 2SD1210
2SC2824	Si-N	NF-Tr-L, 120V, 1A, 15W, 120MHz	14h	Tos	2SC2690(A), 2SC3117, 2SD669

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2SC2825	Si-N	hi-beta, 80V, 6A, 70W, B>500	16j	Sak	2SD1831
2SC2826	Si-N	S-L, 500/400V, 3A, 40W, 20MHz	17j	Shi	BUT56(A), BUT92, TIP75C, 2SC3038, ++
2SC2827	Si-N	S-L, 500/400V, 6A, 50W, 20MHz	17j	Shi	BUT54, BUT56(A), 2SC3830, 2SC4106, ++
2SC2828	Si-N	S-L, 500V, 10A, 100W	18j	Shi	BUV47(A), BUW12(A), 2SC2789, 2SC3042++
2SC2829	Si-N	S-L, 500/400V, 10A, 100W, <1/2,5µs	23a	Shi	BUW25..28, BUW34..36, 2SC3046, ++
2SC283(H)	Si-N	=2SC281: 50V, 0,35W	2a	Hit	BC187, BC182, BC237, BC547, 2SD767++
2SC2830	Si-N	S-L, 500/400V, 20A, 200W, <1/2,5µs	23a	Shi	2SC3085, 2SC3094, 2SC3593
2SC2831	Si-N	S-L, 800/500V, 1,5A, 25W	17j	Mat	BUV36(A), BUX84..85, 2SC3149, 2SC3352
2SC2831A	Si-N	=2SC2831: 900/500V	17j		BUV36A, BUX85, 2SC3149, 2SC3531, ++
2SC2832	Si-N	S-L, 800/500V, 5A, 40W	17j	Mat	BUT11(A), BUV46(A), 2SC3047, 2SC3050++
2SC2832A	Si-N	=2SC2832: 900/500V	17j		BUT11A, BUV46A, 2SC3050
2SC2833	Si-N	S-L, 800/500V, 5A, 100W	18j	Mat	BUW11(A), BUW131(A), 2SC3153, 2SC3232+
2SC2833A	Si-N	=2SC2833: 900/500V	18j		BUW11A, BUW131A, 2SC3153, 2SC3232, ++
2SC2834	Si-N	S-L, 800/500V, 7A, 100W	18j	Mat	BUV47(A), BUW12(A), 2SC3450, 2SC3797, +
2SC2834A	Si-N	=2SC2834: 900/500V	18j		BUV47A, BUW12A
2SC2837	Si-N	NF/S-L, 150V, 10A, 100W, 70MHz	18j	Sak	2SC2987A, 2SC3907, 2SD1047, 2SD1703, ++
2SC2838	Si-N	=2SC2837: 12A, 120W	20j		SC2525, 2SC2565, 2SC2766, 2SC2921, ++
2SC2839	Si-N	FM/VHF, 30V, 30mA, 320MHz	40c	Say	BF225, BF314, BF502, BF505, BF959++
2SC284(H)	Si-N	=2SC281: 70V, 0,35W	2a	Hit	BC174, BC182, BC190, BC546, 2SC1890+
2SC2840	Si-N	VHF, 25V, 30mA, 600MHz	40c	Say	BF225, BF314, BF502, BF505, BF507++
2SC2841	Si-N	S-L, 500/400V, 7A, 70W, <1/4µs	18j	Mat	BU428(A), TIP58A, 2SC2788, 2SC3040, ++-
2SC2843	Si-N	UHF-Tuner		Mat	—
2SC2844	Si-N	UHF, 25V, 0,07A, 4,5GHz	25p	Mat	BFP98, BFQ73, 2SC3302
2SC2845	Si-N	SMD, UHF, ra, 25V, 0,07A, 4,5GHz	35a	Mat	2SC3161, 2SC3774..75
2SC2847	Si-N	SMD, VHF, re, 30V, 0,02A, >600MHz	35a	Mat	BF799, 2SC3015, 2SC3374
2SC285	Si-N	VHF-A/Tr, 50V, 0,2A, 0,5W, 320MHz	2a	Fui	BFW16..17, BFX55, 2SC2852
2SC2850	Si-N	UHF-L, 35V, 3A, PQ=11W(860MHz)	56r	Nec	2SC2559
2SC2851	Si-N	VHF-O/Tr, 36V, 0,3A, PQ=0,9W(175MHz)	7c(9mm)	Mat	2SC2053
2SC2852	Si-N	UHF-O/Tr, 36V, 0,5A, PQ=1W(470MHz)	2a	Mat	BFS50, MRF829, 2N3948, 2SC2762, ++
2SC2853	Si-N	Uni, 90V, 0,1A, 0,4W, 310MHz	7c	Hit	2SC1775(A), 2SC2240, 2SC2459, 2SC3245, ++
2SC2854	Si-N	=2SC2853: 120V	7c		2SC1775(A), 2SC2240, 2SC2459, 2SC3245, ++
2SC2855	Si-N	=2SC2853: ra	7c		2SC1775(A), 2SC2240, 2SC2369, 2SC2459, ++
2SC2856	Si-N	=2SC2853: ra, 120V	7c		2SC1775A, 2SC2240, 2SC2389, 2SC2459, ++
2SC2857	Si-N	NF/VA-Tr, 180V, 0,05A, 0,5W, >50MHz	7c	Say	BF298..299, BF422, BFR88..99, ++
2SC2858	Si-N	S-L, 500V, 6A, 65W, <1/3,5µs	20j	Hit	2SC2650, 2SC2818
2SC2859	Si-N	SMD, Uni, 36V, 0,5A, 300MHz	35a	Tos	BC817..818, BCX19..20, 2SC3341, ++
2SC285A	Si-N	=2SC285: 0,3A, 500MHz	2a		BFX55, 2SC2852
2SC286	Si-N	FM/VHF, 20V, 10mA, >600MHz	24b	Nec	BF362..363
2SC2860	Si-N	FM/VHF, 650MHz	40c	Mat	BF225, BF314, BF502, BF505, BF507++
2SC2865(A)	Si-N	S-L, 250V, 20A, 200W, <0,9/1,9µs	23a	Shi	BUV11..12, BUX11..12, BUW58, BUW73
2SC2867	Si-N	S-L, 300V, 10A, 50W, <1/1,5µs	17j	Hit	BUS37, BUV27A..28, 3SC3057, 2SC3562
2SC2868	Si-N	Uni, 80V, 0,1A, 0,4W, 200MHz	7c	Tos	BC548, 2SC2240, 2SC2459, 2SC3245(A), ++
2SC2869	Si-N	UHF, ra, 20V, 0,08A, 0,4W, 8GHz	25q	Nec	2SC2876
2SC287(A)	Si-N	FM/VHF, 20(A=35)V, 10mA, >600MHz	24b	Nec	BF362..363
2SC2870	Si-N	NF/Vid-E, 300V, 0,1A, 10W, 80MHz	30j	Hit	2SC2924, 2SC3408, 2SC3805, 2SC4019, ++
2SC2871	Si-N-Darl	NF/S-L, 80V, 1A, 8W, B>2000, <0,2/5µs	30j	Hit	2SD1598, 2SD1759, 2SD1600, 2SD1980, ++,
2SC2872(S)	Si-N	Uni, 50V, 0,7A, 0,3..0,4W, 120MHz	7c, 40c	Rhm	BC337, BC637, BC839, 2SD667, ++
2SC2873	Si-N	SMD, Uni, 50V, 2A, 100MHz, 0,1/1, 1µs	39b	Tos	2SD1422, 2SD1623
2SC2875	Si-N	HF/S, 35V, 0,1A, 0,2W, 400MHz	41c	Tos	BSW41, BSY83, 2N708, 2N4123..24, ++
2SC2876	Si-N	UHF, ra, 15V, 0,08A, 0,2W, 7GHz	25q	Tos	2SC2876, 2SC3358, 2SC3603
2SC2877	Si-N	NF-L, 40V, 3A, 10W, 100MHz	14h	Tos	BD785, BDX35..37, 2SD826, 2SD1348, ++
2SC2878	Si-N	hi-Ueb, S, 50V, 0,3A, 0,4W, 30MHz	7c	Tos	2SC3615, 2SC3836, 2SD1915, (2N2221..22++)
2SC2879	Si-N	AM-L, 45V, 25A, PEP=100W(28MHz)	59r	Tos	—
2SC288(A)	Si-N	UHF-O, 30(A=35)V, 20mA, >850MHz	24b	Nec	BF362..363
2SC2880	Si-N	SMD, Vid, 200V, 0,05A, 120MHz	39b	Tos	BF620, BF622, BFN20, 2SC3380, ++
2SC2881	Si-N	SMD, Uni, 120V, 0,6A, 120MHz	39b	Tos	2SD1007, 2SD1418..1419
2SC2882	Si-N	SMD, Uni, 80V, 0,4A, 100MHz	39b	Tos	2SC3436, 2SD875, 2SD968(A)
2SC2883	Si-N	SMD, Uni, 30V, 1,5A, 120MHz	39b	Tos	2SC2873, 2SC2982, 2SD1621
2SC2884	Si-N	SMD, Uni, 35V, 0,6A, 120MHz	39b	Tos	BCX54..56, 2SC3444, 2SC4376, 2SD1882, ++
2SC2885	Si-N	S-L, 330V, 2A, 15W, <1/3µs	30j	Nec	2SC2946, 2SC3233, 2SC3631, 2SC4818
2SC2886	Si-N	VHF-L, 55V, 0,75A, PQ=5W(175MHz)	55s	Nec	BLY91, BLY97
2SC2887	Si-N	VHF-L, 55V, 1,5A, PQ=14W(175MHz)	55s	Nec	BLY92
2SC2888	Si-N	VHF-L, 55V, 3A, PQ=28W(175MHz)	55s	Nec	—
2SC2889	Si-N	VHF-L, 55V, 6A, PQ=40W(175MHz)	55s	Nec	BLW25, 2N5643, 2SC2192
2SC289	Si-N	UHF-V/M, 25V, 10mA, >900MHz	24b	Nec	BF362..363
2SC2890	Si-N	VHF-L, 55V, 12A, PQ=84W(175MHz)	57s	Nec	MRF317

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2SC2891	Si-N	VHF-L,55V,15A,PQ=112W(175MHz)	57s	Nec	2SC2609
2SC2892	Si-N	UHF-L,55V,0,75A,PQ=4W(400MHz)	55s	Nec	BLW90,BLY37
2SC2893	Si-N	UHF-L,55V,1,5A,PQ=10,7W(400MHz)	55s	Nec	BLW91
2SC2894	Si-N	UHF-L,55V,3A,PQ=22,4W(400MHz)	55s	Nec	BLX95,2N6105
2SC2895	Si-N	UHF-L,55V,6A,PQ=40W(400MHz)	57s	Nec	2SC2796
2SC2896	Si-N	UHF-L,55V,12A,PQ=63W(400MHz)	57s	Nec	2SC2186
2SC2897	Si-N	UHF-L,55V,15A,PQ=100W(400MHz)	57s	Nec	—
2SC2898	Si-N	S-L,500/400V,8A,50W	17j	Hit	BU406,BUT56(A),2SC3039,2SC4106,++
2SC2899	Si-N	S-L,500/400V,0,5A,10W,<1/3µs	14h	Hit	BD410,BUX88..87,2SC3051,2SC3425
2SC29	Si-N	=2SC28:0,025A,0,115W	2a	Fui	BC187,BC182,BC237,BC547,2N2218++
2SC290	Si-N	FM/VHF-L,70V,2A,PQ=6W(100MHz)	2a	Nec	—
2SC2900	Si-N	S-L,350V,4A,90W,10MHz	18j	Sak	BU426(A),BUW11(A),TIP51..54,++
2SC2901	Si-N	SS,40V,0,2A,0,8W,<12/18ns	7e	Nec	BSS11,BSX19..20,2N2368..69(A),++
2SC2902	Si-N	S-L,800/400V,15A,150W,<1,5/4,5µs	23a	Org	BUS13(A),BUW45..46,BUX46(A..C),++
2SC2903	Si-N	S-L,800/400V,25A,200W,<1,5/4,5µs	23a	Org	BUS14(A),BUS98(A),2SC3094,2SC3593
2SC2904	Si-N	AM-L,50V,22A,PQ=110W(30MHz)	57s	Mit	—
2SC2905	Si-N	UHF-L,35V,15A,PQ=50W(520MHz)	57s	Mit	2SC3102
2SC2906	Si-N	UHF-L,25V,2,2A,PQ=6,3W(500MHz)	58r	Nec	—
2SC2906A	Si-N	=2SC2906:3A,PQ=7W(500MHz)	56r		—
2SC2907	Si-N	S-L,400V,5A,40W,<2/5,5µs	17j	Fjd	BU406,BU408,MJE52T..53T,2SC3056,++
2SC2908	Si-N	S-L,200V,5A,50W,<0,5/3µs	16j	Nec	BD243F,BUW11(A),TIP51..54,2SC2809,++
2SC2909	Si-N	Uni,180V,0,07A,0,6W,150MHz	7c	Say	BF298..299,BF422A,2SC3248,++
2SC291	Si-N	NF/S,70V,3A,1W,90MHz	2a	Son	2N4236..4239,2SC2214
2SC2910	Si-N	Uni,180V,0,07A,0,9W,150MHz	7c(9mm)		BF422A,2SC3248..49,2SC3467
2SC2911	Si-N	Uni-L,180V,0,14A,10W,150MHz	14h	Say	BF415,BF417,MJE340,2SC3416,++
2SC2912	Si-N	=2SC2911:200V	14h		BF415,BF417,MJE340,2SC3418,++
2SC2913	Si-N	S-L,500/400V,7A,40W,<1/3,5µs	22a	Tos	BUT56(A),2SC2739,2SC3039,2SC4108,++
2SC2914	Si-N	S-L,500/400V,10A,120W,<1/3,5µs	23a	Tos	BUW25..26,BUW34..36,2SC3043,++
2SC2915	Si-N	UHF-L,35V,20A,175W,PQ=86W(500MHz)	57s	Nec	—
2SC2917	Si-N	VHF-L,35V,20A,175W,PQ=83W(175MHz)	57s	Nec	—
2SC2918	Si-N	UHF-L,35V,5A,PQ=21W(860MHz)	58r	Nec	—
2SC292(S)	Si-N	=2SC291:100V	2a	Son	2N4239,2SC2214
2SC2920	Si-N	S-L,Reg-L,450V,15A,150W,30MHz	23a	Fui	BUV25,BUW44,BUX25,2SD641,++
2SC2921	Si-N	NF/S-L,160/180V,15A,150W,60MHz	20j	Sak	2SC2526,2SC2565,2SC2786(A),2SC2921,++
2SC2922	Si-N	NF/S-L,180/180V,17A,200W,50MHz	20j	Sak	2SC2774,2SC3264,2SC3856
2SC2923	Si-N	Vid-L,300/300V,0,1A,15W,140MHz	13j	Mat	(BF817,BF758..759,BF859,++)
2SC2924	Si-N	=2SC2923:	30j		2SC2870,2SC3408,2SC3805,2SC4019,++
2SC2925	Si-N	hi-Ueb,hi-beta,60V,0,7A,0,75W,200MHz	7c	Mat	2SD1532,2SD1779
2SC2926(S)	Si-N	VHF-M/O,UHF-O,30V,50mA1100MHz	7c,41c	Rhm	BF357,BF377..373,BF639,BF763,++
2SC2927	Si-N	Vid-L,300V,0,2A,10W,80MHz	≈17j	Hit	2SC1505..1507,2SC1755..1757,2SC1905
2SC2928	Si-N	CTV-HA,1500/800V,5A,50W	23a	Hit	BU208(A),BU508(A),2SD792,2SD954,++
2SC2929	Si-N	S-L,450/400V,3A,40W,<1,5/2,8µs	17j	Fjd	BUT93,TIP75B,C,2SC2826,2SC3038,++
2SC293(S)	Si-N	=2SC291:130V	2a	Son	BUX49..50,BUY41
2SC2930	Si-N	S-L,500/400V,30A,200W,<1/4µs	23a	Fjd	BUS14(A),BUS96(A),2SC3058
2SC2931	Si-N	UHF-L,35V,0,8A,PQ=1,7W(900MHz)	56s	Mit	—
2SC2932	Si-N	UHF-L,35V,2A,PQ=7W(900MHz)	58s	Mit	—
2SC2933	Si-N	UHF-L,35V,4A,PQ=16W(900MHz)	58s	Mit	—
2SC2934	Si-N	NF/Vid-L,300V,0,2A,12,5W,80MHz	14h	Hit	BF417,BF459,2SC2621,2SC3417,++
2SC2935	Si-N	=2SC2934:15W	14h		BF417,BF459,2SC2621,2SC3417,++
2SC2936	Si-N	S-L,500/400V,30A,150W,<1/4µs	23a	Hit	BUS14(A),BUS98(A),2SC3056
2SC2937	Si-N	S-L,500/400V,8A,80W,<1/3,7µs	16j	Shi	BU926,TIP58A,2SC2788,2SC3040,++
2SC2938	Si-N	S-L,500/400V,10A,100W,<1/3,7µs	16j	Shi	BUV47(A),BUW12(A),2SC2789,2SC2828++
2SC2939	Si-N	S-L,500/400V,10A,100W,<1/2,5µs	16j	Shi	BUV47(A),BUW12(A),2SC2789,2SC2828++
2SC294(-M)	Si-N	DuaL,25V,0,05A0,6W,200MHz	TO-80	Nec	—
2SC2940	Si-N	S-L,230/230,30A,300W,<0,9/2µs	68a	Shi	2SC1301,2SC2249,2SC2445,2SC3224,++
2SC2941	Si-N	UHF-O,25V,0,22A,5,5W,6GHz		Nec	—
2SC2942	Si-N	S-L,230/230,50A,200W,<1,2/2µs	68a	Sak	2SC1437
2SC2943	Si-N	S-L,390/250V,15A,80W,70MHz	18j	Son	BUV48(A..C),BUW13(A),2SC3435,++
2SC2944	Si-N	S-L,250/200V,15A,100W,<0,8/1,9µs	18j	Fjd	BUV48(A..C),BUW13(A),2SC3435,++
2SC2946	Si-N	S-L,330/200V,2A,15W,<1/3µs	30j	Nec	2SC2885,2SC3233,2SC3631,(BUV93..95)
2SC2947	Si-N	Uni,80V,0,1A,0,25W,250MHz	40c	Nec	BC174,BC182,BC190,BC546,++
2SC2948	Si-N	S-L,500/400V,50A,300W,<1/4µs	≈74	Hit	—
2SC2949	Si-N	UHF-O,25V,0,11A,2,75W,6,5GHz		Nec	—
2SC295	Si-N	DuaL,15V,0,05A,0,6W,200MHz	TO-80	Nec	—
2SC2950	Si-N	UHF-O,25V,0,22A,5,5W,6GHz		Nec	—
2SC2951	Si-N	UHF-O,25V,0,44A,9,7W,5,5GHz	62b	Nec	—

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2SC2952	Si-N	UHF, 30V, 0,25A, 2,5GHz	5g	Nec	2SC1199, 2SC1252, 2SC1365..66
2SC2953	Si-N	UHF, 30V, 0,25A, 5W	55s	Nec	BFR65, 2SC1249..1251
2SC2954	Si-N	SMD, VHF, 35V, 0,15A, 4000MHz	39b	Nec	—
2SC2955	Si-N	VHF, 15V, 5mA, 0,05W, 4GHz	51s	Nec	BFQ59..60, BFQ70..71, 2SC2143
2SC2956	Si-N	VHF-L, 45V, 0,6A, PQ=1,6W(2,3GHz)	55r	Nec	—
2SC2957	Si-N	VHF-L, 45V, 1,2A, PQ=2,8W(2,3GHz)	55r	Nec	—
2SC2956	Si-N	Uni, 160/140V, 0,5A, 1W, 60MHz	9b	Nec	2SC2363, 2SC3228, 2SC3332
2SC2959	Si-N	=2SC2956: 160/160V	9b		2SC2383, 2SC3228, 2SC3332
2SC296	Si-N	HF-VM/O, 20V, 25mA, 0,2W, 180MHz	5g	Fui	BF240..241, BF254..255, BF594..595,++
2SC2960	Si-N	S, 60V, 0,15A, 0,25W, <190/700ns	40c	Say	BSV59, BSX49, 2N3301..02, 2N3903..04++
2SC2961	Si-N	S-L, 400/300V, 10A, 80W, <0,4/1,9µs	18j	Fjd	BUV47(A), BUW12(A), 2SC2828, 2SC3042++
2SC2962	Si-N	S-L, 700/600V, 5A, 60W, <0,5/3µs	18j	Fjd	BU426(A), BUW11(A), 2SC3153, 2SC3798++
2SC2963	Si-N	S-L, 70V, 3A, 40W, <0,5/4,2µs	17j	Shi	2SC3252, (BD241A, BD537, BD937,++)
2SC2964	Si-N	S-L, Reg-L, 600/400V, 15A, 150W, 28MHz	23a	Fui	BUS13(A), BUW45..48, BUX48(A..C)
2SC2965	Si-N	=2SC2964: 600/450V	23a		BUS13(A), BUW45..46, BUX48(A..C)
2SC2968	Si-N	S-L, 225/225V, 40A, 200W, <1/2µs	88a	Nec	2SC2403, 2SC2366, 2SC2973, 2SD702
2SC2967	Si-N	FM, 600MHz	40c	Nec	FBF225, BF310, BF314, BF502, BF505++
2SC2968	Si-N	AM, 250MHz	40c	Nec	BF240..241, BF254..255, BF594..595,++
2SC2969	Si-N	UHF-L, 36V, 4A, PQ=15W(470MHz)	61s	Fui	—
2SC297	Si-N	=2SC291: 10W	43m	Son	(BD787, BD789, MJE240..242,++)
2SC2970	Si-N	S-L, 3007200V, 5A, 40W, <1,5/4,5µs	22a	Org	BU406..408, MJE51T..53T, 2SC2907,++
2SC2971	Si-N	S-L, 300/200V, 10A, 100W, <1,5/4,5µs	23a	Org	BUW72, BUX17AC, BUX43, BUY18,++
2SC2972	Si-N	S-L, 300/200V, 15A, 150W, <1,5/4,5µs	23a	Org	BUX13, BUY50, MJ15022, MJ15024,++
2SC2973	Si-N	S-L, 300/200V, 40A, 200W, <1,5/4,5µs	68a	Org	2SC2366, 2SC2403, 2SD642, 2SD702
2SC2974	Si-N	S-L, 300/200V, 70A, 300W, <1,5/4,5µs	≈74	Org	—
2SC2975	Si-N	S-L, 600/400V, 5A, 40W, <1,5/4,5µs	22a	Org	BUT11(A), BUV46(A), 2SC3047, 2SC3087++
2SC2976	Si-N	S-L, 800/400V, 10A, 100W, <1,5/4,5µs	28a	Org	BUS12(A), BUW26, BUW35..36, BUX81,++
2SC2977	Si-N	S-L, 800/400V, 30A, 200W, <1,5/4,5µs	68a	Org	2SC2204, 2SD295
2SC2978	Si-N	S-L, 800/400V, 50A, 200W, <1,5/4,5µs	≈74	Org	—
2SC2979	Si-N	S-L, 900/600V, 3A, 40W, <1/4µs	17j	Hit	BUT11A, BUT56A, BUV46A, 2SC3150,++
2SC298	Si-N	=2SC292: 10W	43m	Son	(BD791, MJE243..244,++)
2SC2980	Si-N	S-L, 900/800V, 5A, 80W, <1/4µs	20j	Hit	—
2SC2981	Si-N	S-L, 900/800V, 8A, 100W, <1/4µs	23a	Hit	BU526, BU536, BUV47A, BUW12A,++
2SC2982	Si-N	SMD, lo-sat, 30V, 2A, 150MHz	39b	Tos	2SD1821, 2SD1823
2SC2963	Si-N	NF/S-L, 160V, 1,5A, 15W, 100MHz	30j	Tos	2SC4027, 2SD1033, 2SD1080..82, 2SD1918
2SC2984	Si-N	UHF-L, 45V, 6A, PQ=25W(890MHz)	82a	Nec	—
2SC2985	Si-N	UHF-L, 45V, 2A, PQ=7,9W(890MHz)	55s	Nec	—
2SC2986	Si-N	HF, 40V, 0,05A, 0,3W, 350MHz	7c	Tos	BF370, BF920..921S, BF959
2SC2987	Si-N	NF-L, 140/140V, 12A, 120W, 50MHz	16j	Nec	2SD1047
2SC2987A	Si-N	=2SC2987: 180/180V	18j		2SD1047
2SC2988	Si-N	VHF-L, 36V, 0,5A, PQ=2,2W(175MHz)	14h	Mat	—
2SC2989	Si-N	VHF-L, 36V, 1A, PQ=10,5W(175MHz)	17l(E=case)	Mat	—
2SC299	Si-N	=2SC293: 10W	43m	Son	(BDX36..37)
2SC2990	Si-N	VHF-E, PQ>2,5W(150MHz)		Mat	—
2SC2991	Si-N	UHF-L, 36V, 0,6A, PQ=2,3W(470MHz)	58s	Mat	—
2SC2992	Si-N	UHF-L, 36V, 1,5A, PQ=11W(470MHz)	58s	Mat	—
2SC2995	Si-N	=2SC2986: 0,2W	41c	Tos	→2SC2988
2SC2998	Si-N	=2SC2966: SMD	35a	Tos	BF599, BF799, BFS20, 2SC3015,++
2SC2997	Si-N	UHF, 20V, 0,06A, 0,35W, 8GHz	52s	Nec	2SC2876, 2SC3062, 2SC3358, 2SC3603
2SC2998	Si-N	=2SC2960: 0,5W	7c	Say	→2SC2960
2SC2999	Si-N	VHF, 25V, 30mA, 750MHz	40c	Say	BF225, BF314, BF502, BF505, BF959++
2SC30	Si-N	VHF, 60V, 0,08A, 0,5W, 280MHz	2a	Nec	BFW18..17, BFX55, 2N3725, 2SC1385,++
2SC300	Si-N	HF/Uni, 25V, 0,1A, 0,26W, 400MHz	2a	Mit	BSW41, BSY62..63, 2N706A, 2N708,++
2SC3000	Si-N	=2SC2839: 0,25W	7c	Say	→2SC2839
2SC3001	Si-N	VHF-L, 20V, 3A, PQ=7W(175MHz)	58s	Mit	2SC1729
2SC3004	Si-N-Darl	NF/S-L, 30V, 3A, 10W, B>2000	14h	Hit	BD675, BD775, 2N6037..6039,++
2SC3005	Si-N	SMD, UHF-O, 15V, 0,05A, 1600MHz	35a	Hit	BFS17, 2SC3016
2SC3006	Si-N	UHF-L, 35V, 1A, PQ>3W(470MHz)	58s	Tos	2SC3020
2SC3007	Si-N	lo-sat, 50V, 2A, 8W(Tc=25°), 100MHz	2a	Tos	(BC440..441, BSS15..18, 2N5320..21,++)
2SC3008	Si-N	VHF-L, 35V, 10A, PQ=40W(175MHz)	56r	Nec	—
2SC3009	Si-N	UHF-L, 25V, 1,5A, PQ=3,5W(860MHz)	58r	Nec	—
2SC301	Si-N	=2SC300	2a	Mit	BSW41, BSY62..63, 2N706A, 2N708,++
2SC3010	Si-N	UHF-L, 25V, 3A, PQ=5,5W(860MHz)	56r	Nec	—
2SC3011	Si-N	SMD, UHF, 20V, 0,03A, 6,5GHz	35a	Tos	2SC3583, 2SC3585
2SC3012	Si-N	NF/S-L, 130V, 10A, 100W, 60MHz	16j	Nec	2SC2708, 2SC2837, 2SC2967(A)
2SC3013	Si-N	SMD, VHF-O, 15V, 0,05A, 900MHz	35a	Hit	BF599, BF798, BFS202SC3015

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2SC3014	Si-N	SMD, UHF-V, 15V, 0,05A, 3,4GHz	35a	Hit	BFT75
2SC3015	Si-N	SMD, VHF, 15V, 0,05A, 1100MHz	35a	Hit	BF599, BF799, BFS20
2SC3016	Si-N	SMD, VHF/UHF-O, 10V, 0,05A, 1450MHz	35a	Hit	BFS17, 2SC3005
2SC3017	Si-N	VHF-Tr/E, 20V, 0,6A, PQ=1,7W(175MHz)	2a(E=case)	Mit	—
2SC3018	Si-N	VHF-L, 20V, 1,5A, PQ=3,5W(175MHz)	58s	Mit	—
2SC3019	Si-N	UHF-A/Tr, 35V, 0,4A, PQ=0,6W(520MHz)	25q	Mit	BLW12
2SC302	Si-N	=2SC300: 50V	2a	Mit	BSV59, BSX48..49, 2N3903..3904, ++
2SC3020	Si-N	UHF-L, 35V, 1A, PQ=3,3W(520MHz)	58s	Mit	2SC3006
2SC3021	Si-N	UHF-L, 35V, 2A, PQ=8W(520MHz)	58s	Mit	2SC1967
2SC3022	Si-N	UHF-L, 35V, 7A, PQ=22W(520MHz)	58s	Mit	2SC2695
2SC3023	Si-N	TV-HA, 1500V, 3A, 50W, <2/5,5µs	23a	Hit	BU208..209(A), BU508(A), 2SD850, ++
2SC3024	Si-N	=2SC3023: 1700/800V	23a		BU209(A), 2SD784..785
2SC3025	Si-N	TV-HA, 1500/800V, 6A, 50W, <1,5/5,5µs	23a	Hit	BU208(A), BU508(A), 2SD649, 2SD621, ++
2SC3026	Si-N	=2SC3025: 1700/800V	23a		—
2SC3027	Si-N	TV-HA, 1500/800V, 8A, 50W, <2/5,5µs	23a	Hit	BU508(A), BU908
2SC3028	Si-N	=2SC3027: 1700/800V	23a		—
2SC3029	Si-N	UHF, 15V, 5mA, 0,05W, 4GHz	25q	Nec	BFG90..91, BFQ85
2SC303	Si-N	HF/Uni, 50V, 0,5A, 0,8W, 200MHz	2a	Mit	BC140..141, BC300..302, 2N3053, ++
2SC3030	Si-N-Darl	S-L, 900/800V, 7A, 80W, B=15	18j	Fjd	—
2SC3031	Si-N-Darl	=2SC3030:	23a		BUT18
2SC3032	Si-N-Darl	=2SC3030: 900/700V	18j		—
2SC3033	Si-N-Darl	=2SC3030: 900/700V	23a		BUT18
2SC3034	Si-N	S-L, 250/200V, 10A, 100W, <1/3µs	23a	Org	BUX17(A..C), BUX42..43, BUY18, ++
2SC3035	Si-N	S-L, 300/200V, 5A, 40W, <1,5/4,5µs	22a	Org	BU406..406, 2N6234..35, 2SC2907, ++
2SC3036	Si-N	=2SC3035: 800/400V	22a		BUT11(A), BUV48(A), 2SC3047, 2SC3087++
2SC3037	Si-N	UHF, 20V, 0,07A, 0,4W, 5GHz	7f	Son	2SC2570(A), 2SC3337, 2SC3606
2SC3038	Si-N	S-L, 500/400V, 4A, 40W, <1/3,5µs	17j	Say	BUT11(A), BUV46(A), 2SC2827, 2SC3497++
2SC3039	Si-N	S-L, 500/400V, 7A, 50W, <1/3,5µs	17j	Say	BUT56(A), BUT54, 2SC2739, 2SC3170++
2SC304	Si-N	HF/Uni, 60V, 0,5A, 0,8W, 220MHz	2a	Mit	BC140..141, BC300..302, 2N3053, ++
2SC3040	Si-N	S-L, 500/400V, 8A, 80W, <1/3,5µs	18j	Say	BU902..903, TIP58A, 2SC2536, 2SC2788++
2SC3041	Si-N	=2SC3040:	23a		BU526, BU536, 2SC2536, 2SC2788, ++
2SC3042	Si-N	S-L, 500/400V, 12A, 100W, <1/3,5µs	18j	Say	BUW13(A), BUV48(A..C), 2SC3520, ++
2SC3043	Si-N	=2SC3042: 120W	23a		BUW75..77, 2SC3411, 2SC3451, 2SD641, ++
2SC3044	Si-N	S-L, Reg-L, 450/400V, 8A, 100W, 30MHz	23a		BU426(A), BU528, BUX44, 2SD640, ++
2SC3044A	Si-N	=2SC3044: 450/450V	23a		BU426(A), BU526, BUX44, 2SD640, ++
2SC3045	Si-N	S-L, Reg-L, 450/400V, 10A, 100W, 32MHz	23a	Fui	BUW24..26, BUW34..36, 2SC3520, ++
2SC3046	Si-N	S-L, Reg-L, 800/450V, 10A, 100W, 28MHz	23a	Fui	BUW25..26, BUW35..36, 2SC3451, ++
2SC3047	Si-N	S-L, 850/500V, 8A, 40W, <1/4µs	17j	Fjd	BUT11(A), BUT56(A), BUV48(A), ++
2SC3048	Si-N	=2SC3047: 50W	23a		BU426A, BU526, BUX47(A), 2SD611, ++
2SC3049	Si-N	=2SC3047: 10A, 50W	23a		BU626A, BUS12(A), BUW36, 2SD1094, ++
2SC305	Si-N	HF/Uni, 80V, 0,5A, 0,8W, 220MHz	2a	Mit	BC140..141, BC300..301, 2N1990, ++
2SC3050	Si-N	S-L, 1200/800V, 5A, 150W, -/<4,5µs	23a	Fui	BU546, BU903, 2SC3214, 2SC3343, ++
2SC3051	Si-N	S-L, 500/400V, 0,8A, 10W, -/4µs	14h	Tos	BD410, 2SC3425
2SC3052	Si-N	=2SC2320: SMD	35a	Mit	BC846..847, BCW71..72, BCW81, ++
2SC3053	Si-N	=2SC710: SMD	35a	Mit	BF799, BFS20, 2SC3015
2SC3054	Si-N-Darl+Di	S-L, 500/400V, 20A, 100W, <3/4µs	77c(G)	Mat	BU932PFI, BUT13PFI
2SC3055	Si-N	S-L, Reg-L, 450/400V, 2A, 15W, 28MHz	17j	Fui	BUX84..85, 2SC2333, 2SC2534, 2SC2736, ++
2SC3056	Si-N	S-L, Reg-L, 450/400V, 8A, 50W, 30MHz	17j	Fui	BUT11(A), BUV46(A), MJE53T, 2SC2542++
2SC3056A	Si-N	=2SC3056: 450/450V	17j	Fui	BUT11(A), BUV46(A), MJE53T, 2SC2542++
2SC3057	Si-N	=2SC3045: 50W	17j	Fui	BUT76(A), BUV56(A), 2SC3562
2SC3058	Si-N	S-L, Reg-L, 600/400V, 30A, 200W, 30MHz	23a	Fui	BUS14(A), BUS96(A)
2SC3058A	Si-N	=2SC3058: 800/450V	23a		BUS14(A), BUS98(A)
2SC3059	Si-N	S-L, Reg-L, 1200/850V, 2A, 100W, 15MHz	23a	Fui	BU204..206, MJ8500, 2SC1132, 2SD1097++
2SC306	Si-N	Uni, 50V, 0,5A, 0,57W, 240MHz, -/450ns	2a	Mit	BC140..141, BC300..302, 2N3053, ++
2SC3060	Si-N	S-L, Reg-L, 1200/850V, 5A, 100W, 15MHz	23a	Fui	BU207..208(A), MJ8502, 2SD1103, ++
2SC3061	Si-N	S-L, Reg-L, 1200/850V, 10A, 200W, 15MHz	23a	Fui	BU137A, MJ8504..8505, 2SC3215
2SC3062	Si-N	UHF, 25V, 0,065A, 0,4W, 8,5GHz	52s	Nec	2SC3584
2SC3063	Si-N	Vid-L, 300/300V, 0,1A, 140MHz	14h	Mat	BF417, BF459, 2SC3417, 2SC3503, ++
2SC3064	Si-N	DuaL, 55V, 0,15A, 0,5W, 100MHz		Say	—
2SC3065	Si-N	DuaL, 55V, 0,15A, 0,5W, 100MHz			—
2SC3066	Si-N	DuaL, 130V, 0,05A, 0,5W, 130MHz		Say	—
2SC3067	Si-N	DuaL, 130V, 0,06A, 0,5W, 180MHz			—
2SC3068	Si-N	hi-Ueb, hi-beta, lo-sat, 30V, 0,3A, B>800	7c	Say	2SC3576, 2SC3836
2SC3069	Si-N	hi-Ueb, hi-beta, 80V, 0,2A, B>800	7c	Say	2SC2925, 3SC3638, 2SC3071
2SC307	Si-N	=2SC306: 80V	2a	Mit	BC140..141, BC300..301, 2N1990, ++
2SC3070	Si-N	hi-Ueb, hi-beta, 30V, 1,2A, B>800	7c(9mm)	Say	2SC4369, 2SD1561..82, 2SD1779

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2SC3071	Si-N	hi-Ueb, hi-beta, lo-sat, 120V, 0,2A, B>500	7c(9mm)	Say	—
2SC3072	Si-N	NF/S-L, 50V, 5A, 10W, 100MHz	30j	Tos	2SC3074, 2SC3518, 2SC3592, 2SD1803
2SC3073	Si-N	NF/S-L, 30V, 3A, 15W, 100MHz	30j	Tos	2SC3386, 2SD1221, 2SD1802
2SC3074	Si-N	NF/S-L, lo-sat, 60V, 5A, 20W, 120MHz	30j	Tos	2SC3303, 2SD1803..5, 2SC4668
2SC3075	Si-N	S-L, 500/400V, 0,8A, 10W, -/<4µs	30j	Tos	2SC3363, 2SC3632
2SC3076	Si-N	NF/S-L, lo-sat, 50V, 2A, 10W, 60MHz	30j	Tos	2SD1601..02, (2SD1078, 2SD1221,++)
2SC3077	Si-N	SMD, VHF/UHF, 30V, 20mA, 1100MHz	35a	Mat	BFS17, 2SC3005, 2SC3016, 2SC3161
2SC3078(M)	Si-N	AM/FM, 40V, 0,1A, 0,25W, 230MHz	9c	Rhm	BF240..241, BF254..255, BF594..595,++
2SC3079(M)	Si-N	FM, 25V, 20mA, 0,15W, 500MHz	9c	Rhm	BF225, BF310, BF314, BF502..503,++
2SC308	Si-N	=2SC306: 100V, 90MHz	2a	Mit	BC141, BC300, 2N1889..90, 2N1893(A),++
2SC3080(M)	Si-N	VHF-M/O, UHF-O, 30V, 50mA, 1100MHz	9c	Rhm	BF377..378, BF689, BF763, 2N2857,++
2SC3081	Si-N	VHF/UHF, 1100MHz	7f	Rhm	BF377..378, BF689, BF763, 2N2857,++
2SC3082	Si-N	SMD, VHF-M/O, UHF-O, 30V, 50mA, 1100MHz	≈35b	Rhm	—
2SC3082K	Si-N	=2SC3082:	35a		BF771, BFR35, 2SC3014, 2SC3018,++
2SC3083	Si-N	S-L, 500/400V, 8A, 60W, <1/3,5µs	18j	Say	BU426(A), BUW11(A), 2SC2962, 2SC2536++
2SC3084	Si-N	=2SC3083: 70W	23a		BU426(A), BU528, BUW11(A), 2SC3041,++
2SC3085	Si-N	S-L, 500/400V, 25A, 180W, <1/3,5µs	23a	Say	BUS14(A), BUS98(A), 2SC2830, 2SC3058
2SC3086	Si-N	S-L, 800/500V, 3A, 40W, <1/4µs	17j	Say	BUT11(A), BUV46(A), 2SC3148, 2SD841,++
2SC3087	Si-N	S-L, 800/500V, 5A, 50W, <1/4µs	17j	Say	BUT11(A), BUV46(A), 2SC3047, 2SC3353++
2SC3088	Si-N	S-L, 800/500V, 4A, 60W, <1/4µs	18j	Say	BU428(A), BUW11(A), 2SC3448, 2SC3796++
2SC3089	Si-N	S-L, 800/500V, 7A, 80W, <1/4µs	18j	Say	BU426(A), BU926, 2SC3449, 2SC3536,++
2SC309	Si-N	=2SC306: 120V, 120MHz	2a	Mit	BC300, 2N1893(A), 2N2102, 2N2405,++
2SC3090	Si-N	S-L, 800/500V, 10A, 100W, <1/4143	18j	Say	BUW12(A), BUV47(A), 2SC3450, 2SC3637++
2SC3091	Si-N	S-L, 800/500V, 4A, 70W	23a		BU326(A), BU426(A), BUW11(A),++
2SC3092	Si-N	S-L, 800/500V, 7A, 90W	23a		BU526, BU926, BUS12(A), 2SD811,++
2SC3093	Si-N	S-L, 800/500V, 10A, 120W	23a		BU626A, BUS12(A), BUW35..36,++
2SC3094	Si-N	S-L, 800/500V, 20A, 140W, <1/3,5µs	23a	Say	BUS14(A), BUS98(A), 2SC3593
2SC3095	Si-N	UHF, 25V, 0,11A, 2,75W, 6,5GHz	62b	Nec	—
2SC3096	Si-N	UHF, 25V, 0,22A, 5,5W, 6GHz	62b		—
2SC3098	Si-N	SMD, UHF, ra, 30V, 0,05A, 3,5GHz	35a	Tos	BFT75, 2SC3014
2SC3099	Si-N	SMD, UHF, ra, 20V, 0,03A, 4GHz	35a	Tos	BFQ29, BFR93, BFT75
2SC31(S)	Si-N	VHF, 60V, 0,2A, 0,75W, 200MHz, B>20	2a	Nec	BC140..141, BC300..302, 2N3053,++
2SC310	Si-N	=2SC306: 140V, 120MHz	2a	Mit	BSS43, BSW68, 2N1893A, 2N3019..20
2SC3101	Si-N	UHF-Tr/E, 35V, 1A, PQ=3,5W(520MHz)	2a(E=case)	Mit	—
2SC3102	Si-N	UHF-L, 35V, 18A, PQ=65W(520MHz)	57s	Mit	—
2SC3103	Si-N	UHF-L, 20V, 1,5A, PQ=3,2W(520MHz)	58s	Mit	—
2SC3104	Si-N	UHF-L, 20V, 3A, PQ=7W(520MHz)	58s	Mit	—
2SC3105	Si-N	UHF-L, 35V, 10A, PQ=35W(850MHz)	61v	Mit	—
2SC3106	Si-N	UHF-L, 36V, 0,5A, PQ=2W(940MHz)		Mat	—
2SC3107	Si-N	UHF-L, 36V, 2A, PQ=5W(940MHz)		Mat	—
2SC3108	Si-N	UHF-L, 36V, 2A, PQ=14,5W(940MHz)		Mat	—
2SC3109	Si-N	UHF-Tr/E, 36V, 0,3A, PQ=0,6W(940MHz)	51r	Mat	—
2SC311..312	Si-N			Fui	—
2SC3110	Si-N	SMD, UHF, 15V, 0,03A, 4,5GHz	35a	Mat	BFR92..93, BFT75
2SC3111	Si-N	UHF, 36V, 0,1A, 2W, 2,5GHz	51r	Mat	BFG34, 2SC3368
2SC3112	Si-N	hi-beta, 50V, 0,15A, 0,4W, B=1500	7c	Tos	—
2SC3113	Si-N	=2SC3112: 0,2W	41c		—
2SC3114	Si-N	hi-Ueb, 80V, 0,15A, 0,4W, 100MHz	7c	Say	2SC3071, 2SC3135, (BC546,++)
2SC3115	Si-N	SMD, Uni, ra, 120V, 0,05A, 110MHz	35a	Nec	2SC1622A, 2SC3324, (2SC3340)
2SC3116	Si-N	TV-NF-E, 180/160V, 0,7A, 10W, 120MHz	14h	Say	2SC3117, 2SD868
2SC3117	Si-N	TV-NF-E, 180/160V, 1,5A, 10W, 120MHz	14h	Say	2SD869
2SC3118	Si-N	S, 400V, 0,15A, 0,35W, <300/2300ns	2a	Fui	MPS-A45, 2SC2287, 2SC3469, 2SD1386
2SC3119	Si-N	SMD, UHF-TV-Tuner, re, 900MHz	35a	Tos	BFS17, 2SC3015, 2SC3161, 2SC3374
2SC3120	Si-N	SMD, VHF/UHF-TV-Tuner, re, 2,4GHz	35a	Tos	BFR53, 2SC3014
2SC3121	Si-N	SMD, UHF-Tuner, 1,5GHz	35a	Tos	BFR53, 2SC3013..3018
2SC3122	Si-N	SMD, VHF-TV-Tuner, re, 650MHz	35a	Tos	BF799, 2SC3015, 2SC3374
2SC3123	Si-N	SMD, TV-VHF-M, 1,4GHz	35a	Tos	BFR53, 2SC3014, 2SC3018
2SC3124	Si-N	SMD, VHF-O, TV-Tuner, 1,1GHz	35a	Tos	BFR53, 2SC3014..3018
2SC3125	Si-N	SMD, TV-ZF-E, 600MHz	35a	Tos	(BF599, BF799, BFS20, 2SC3014..3016)
2SC3126	Si-N	VHF/UHF, 20V, 0,05A, 0,2W, 4,5GHz	25q	Hit	BFP91, BFQ72, 2SC3511
2SC3127	Si-N	=2SC3126: SMD	35a		BFT75, 2SC2645, 2SC3161
2SC3128	Si-N	=2SC3128: 0,35W	7f		2SC2570(A), 2SC3037, 3SC3512
2SC3129L,S	Si-N	S-L, 500/400V, 0,5A, 10W, <1/3,5µs	30j	Hit	2SC3075, 2SC3588, (BD410, 2SC3051,++)
2SC313(H)	Si-N	VHF/UHF, 30V, 50mA, 1000MHz	5g	Hit	BF377..378, BF689, BF763, 2N2857,++
2SC3130	Si-N	SMD, VHF/ZF, 15V, 0,05A, 1900MHz	35a	Mat	BFR53, 2SC3014, 2SC3016
2SC3131	Si-N	S-L, 600V, 10A, 100W, <1/5µs	23a	Fjd	BU626A, BUW25..26, BUW35..36, 2SD1094

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2SC3132(L,S)	Si-N-Darl	NF/S-L, 30V, 3A, 10W, B=10000	30j	Hit	2SD1222..23, 2SD1520, 2SD1799, 2SD1817
2SC3133	Si-N	AM-L, 60V, 6A, P0=16W(27MHz)	17k(E=case)	Mit	2SC1945
2SC3134	Si-N	SMD, hi-Ueb, 60V, 0,15A, 100MHz	35a	Say	2SC3689, (BC848, BCV71..72, 2SC3324)
2SC3135	Si-N	hi-Ueb, 60V, 0,2A, 0,25W, 100MHz	40c	Say	2SC3071, 2SC3114
2SC3136	Si-N	TV-VHF-M, 1400MHz	7f	Tos	BF377..378, BF689, BF763, 2N2857, ++
2SC31S7	Si-N	UHF, 30V, 0,05A, 0,2W, 2400MHz	25p	Say	2SC2466, 2SC2353, 2SC2728
2SC3136	Si-N	SMD, S, 200V, 0,05A, 100MHz	35a	Tos	BF820, BF822, BFN22, 2SC3360
2SC3139	Si-N	UHF-L, 50V, 1A, PQ=2,4W(900MHz)	55s	Nec	BLW33
2SC314	Si-N	NF/HF/S, 75V, 1,2A, 20W, 70MHz	2a	Hit	(BD139, BD230, BD377, 2SD1177..1178)
2SC3140	Si-N	UHF-L, 50V, 2A, PQ=5,4W(900MHz)	55s	Nec	BLW98
2SC3141	Si-N	UHF-L, 50V, 4A, PQ=10,7W(900MHz)	55s	Nec	2N4431
2SC3142	Si-N	SMD, FM/VHF, 750MHz	35a	Say	BF599, BF799, 2SC3015, 2SC3374
2SC3143	Si-N	SMD, Uni, 180V, 0,08A, 150MHz	35a	Say	BFN24, BFN26, 2SC3360
2SC3144	Si-N-Darl+Di	S-L, 70V, 3A, 20W, 200MHz, B=5000	17c(A)	Say	BDT83A..C, BDX33B..D
2SC3145	Si-N-Darl+Di	S-L, 70V, 5A, 30W, 200MHz, B=5000	17c(A)	Say	BDT63A..C, BDX33B..D
2SC3146	Si-N-Darl+Di	S-L, 70V, 7A, 40W, B=5000	17c(A)	Say	BDT83A..C, BDX33B..D
2SC3147	Si-N	VHF-L, 36V, 14A, PQ=60W(175MHz)	57s	Tos	BLV75/12, MRF245
2SC3148	Si-N	S-L, Io-sat, 900/800V, 3A, 40W	17j	Tos	—
2SC3149	Si-N	S-L, 900/800V, 1,5A, 40W, 15MHz	17j	Say	BUV36A, BUX85, 2SC3491, 2SC3531, ++
2SC315(H)	Si-N	=2SC314: 80MHz	2a	Hit	(BD139, BD230, BD377, 2SD1177..1178)
2SC3150	Si-N	S-L, 900/800V, 3A, 40W, 15MHz	17j	Say	BUT11A, BUV46A, 2SC3490..3491, ++
2SC3151	Si-N	S-L, 900/800V, 1,5A, 60W, 15MHz	18j	Say	BUW11A, 2SC3285, 2SC3152, 2SC3550, ++
2SC3152	Si-N	S-L, 900/800V, 3A, 80W, 15MHz	18j	Say	BUW11A, 2SC3285, 2SC3152, 2SC3550, ++
2SC3153	Si-N	S-L, 900/800V, 6A, 100W, 15MHz	18j	Say	BUW11A, BUW131A, 2SC3535, 2SC3796A, ++
2SC3154	Si-N	=2SC3151: 70W	23a		BUS11A, BUW11A, BUX46A, 2SC3285, ++
2SC3155	Si-N	=2SC3152: 90W	23a		BUS11A, BUW11A, BUX46A, 2SC3285, ++
2SC3156	Si-N	=2SC3153: 120W	23a		BUS11A, BUX47A, BUX83, 2SD811, ++
2SC3157	Si-N	S-L, 150/100V, 10A, 60W, <0,5/2µs	15j	Nec	BD743E, 2SC4330
2SC3158	Si-N	S-L, 500/400V, 7A, 60W, <1/3,5µs	15j	Nec	BUT56(A), MJE13006..07, 2SC4106, ++
2SC3159	Si-N	S-L, 500/400V, 10A, 80W, <1/3,2µs	15j	Nec	BUV56(A), MJE13008..09, 2SC3562, ++
2SC316	Si-N	Uni, ra, 45V, 0,03A, 0,3W, 50MHz	2a	Mat, Mic	BC184, BC413..414, BC550, 2SC2240, ++
2SC3160	Si-N+Di	S-L, 200/100V, 7,5A, 40W, <2/4µs	15j	Nec	BU406D..408D, 2SC3174, 2SC3176
2SC3161	Si-N	SMD, UHF, 25V, 0,07A, 5GHz	35a	Fui	2SC2645
2SC3182	Si-N	S-L, 500/400V, 3A, 40W, <300/1100ns	17j	Shi	BUT11(A), BUT93, TIP75C, 2SC4105, ++
2SC3163	Si-N	S-L, 500/400V, 8A, 50W, <300/1100ns	17j	Shi	BUT11(A), BUV46(A), 2SC3497, 2SC4106++
2SC3184	Si-N	S-L, 500/400V, 10A, 100W, <300/1100ns	16j	Shi	BUV47(A), BUW12(A), 2SC3435, 2SC4434++
2SC3165	Si-N	S-L, 500/400V, 3A, 60W, <300/1100ns	22a	Shi	BUT93, BUY83..64, 2SC1467, 2SC2626, ++
2SC3166	Si-N	S-L, 500/400V, 6A, 80W, <300/1100ns	22a	Shi	BUT58(A), 2SC3039, 2SC3170, 2SC4108, ++
2SC3167	Si-N	S-L, 500/400V, 10A, 100W, <300/1100ns	23a	Shi	BUW25..26, BUW34..36, 2SC3046, ++
2SC3168	Si-N	S-L, 500/400V, 20A, 200W, <300/1100ns	23a	Shi	2SC3085, 2SC3094, 2SC3593
2SCS169	Si-N	S-L, 500/400V, 2A, 25W, <1/4µs	17c	Mat	BUX84F..85F, 2SC4421, 2SC4533, ++
2SC317(H)	Si-N	S, 70V, 0,1A, 0,35W, <80/200ns	2a	Hit	BF267..299, BFR86, BSS36, BSX21, ++
2SC3170	Si-N	S-L, 500/400V, 7A, 40W, <1/4µs	17c	Mat	BU306F, BUT12(A)F, 2SC4161, 2SC4559, ++
2SC3171	Si-N	S-L, 500/400V, 10A, 100W, <1/4µs	18j	Mat	BUV47(A), BUW12(A), 2SC3435, 2SC4434++
2SC3172	Si-N	UHF, 30V, 0,05A, 0,2W, 1400MHz	25q	Tos	2SC2465, 2SC2470, 2SC2368
2SC3173	Si-N	HV, hi def, 700/400V, 7A, 50W, 40MHz	17c	Say	BU406..408, 2SC3590..91, 2SD684..685
2SC3174	Si-N+Di	=2SC3173: integr. Damper-Di	17j		BU104DP, BU406D..408D
2SC3175	Si-N	=2SC3173: 400/200V	17j		BU104P, BU406, BU408, 2SC3591
2SC3176	Si-N+Di	=2SC3174: integr. Damper-Di,	17j		BU104DP, BU406D, BU408D
2SC3177	Si-N	UHF, 15V, 0,05A, 0,25W, 1900MHz	7c	Mat	BF357, BF377..378, 2SC2570(A), ++
2SC3178	Si-N	=2SC3059: 60W	17j	Fui	BU505, MJE8500..8501
2SC3179	Si-N	NF/S-L, Io-sat, 60V, 4A, 30W, 15MHz	17j	Sak	2SC3253, 2SD1236L, (BD537, BD539B, ++)
2SC317A	Si-N	=2SC317: 100V, 180MHz	2a		FBF297..299, BFR86, BSS39, BSX21, ++
2SC316(A)	Si-N	HF/Uni, 50V, 0,1A, 0,3W, 170MHz	2a	Son	BC237, BC547, 2N2221..22, 2N3903..04++
2SC3180	Si-N	NF/S-L, 80V, 6A, 60W, 30MHz	18j	Tos	BD245B, BDV93, 2SC2706, 2SC2637, ++
2SC3181	Si-N	=2SC3180: 120V, 8A, 80W	18j		BD245C, 2SC2681, 2SC2837, 2SC2987(A), ++
2SC3182	Si-N	=2SC3180: 140V, 10A, 100W	18j		BD245D, 2SC2706, 2SC2637, 2SD1047, ++
2SC3163	Si-N	S-L, 900/800V, 0,2A, 25W, 15MHz	17j	Say	2SC3149, 2SC3675..76, 2SD1527
2SC3184	Si-N	S-L, 900/800V, 0,5A, 30W, 15MHz	17j	Say	2SC3149, 2SC3458, 2SC3676, 2SD1527
2SC3185	Si-N	UHF-Tr/E, 35V, 0,4A, PQ=1,4W(500MHz)	2a	Nec	BFS50, MRF629, 2N3946, 2SC2762
2SC3186	Si-N-Darl	S-L, 200V, 3A, 30W, 60MHz, B=2000	17j	Sak	2SD834, 2SD1073, 2SD1065, 2SD1121, ++
2SC3187	Si-N	Vid, 300/300V, 0,1A, 0,75W, 140MHz	7c	Mat	BF299, BF393, BF420A, 2SC3468, ++
2SC3189	Si-N	HV, hi-def, 700/400V, 7,5A, 50W	17c	Say	BU406..406, 2SC3173, 2SC3175, ++
2SC319	Si-N	VHF-A/Tr, 40V, 0,3A, PQ=1,2W(200MHz)	2a	Nec	BFR96, BFX55, BLW16, MRF225, ++
2SC3190	Si-N	HF, 35V, 0,1A, 0,4W, 120MHz	7c	Kec	BC239, BC548, BF920..921(S), BF959++
2SC3191	Si-N	=2SC3190: 0,2W	41c		BC238, BC546, BF920..921(S), BF959++

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2SC3192	Si-N	FM-ZF, 175MHz	7c	Kec	BF 240..241, BF 254..255, BF 594..595,++
2SC3193	Si-N	=2SC3192:	41c		BF 240..241, BF 254..255, BF 594..595,++
2SC3194	Si-N	FM-V, 550MHz	7c	Kec	BF 225, BF 241, BF 255, BF 314, BF 502++
2SC3195	Si-N	=2SC3194:	41c		BF 225, BF 241, BF 255, BF 314, BF 502++
2SC3196	Si-N	TV-ZF, ra, 530MHz	7c	Kec	BF 198, BF 225, BF 310, BF 367, BF596++
2SC3197	Si-N	TV-ZF, 660MHz	7c	Kec	BF 198..199, BF 224..225, BF 596..597,++
2SC3198	Si-N	Uni, ra, 60V, 0,15A, 0,4W, 130MHz	7c	Kec	2SC1775(A), 2SC2240, 2SC2390, 2SC2459,++
2SC3199	Si-N	=2SC3198: 0,2W	41c		2SC1775(A), 2SC2240, 2SC2390, 2SC2459,++
2SC32(A,AN,M,N)	Si-N	=2SC32: B>40	2a	Nec, Mic	BC 140..141, BC 300..302, 2N3053,++
2SC320	Si-N	VHF-A/Tr, 40V, 0,5A, PQ=2,4W(200MHz)	2a	Nec	BFS 22, BFW 46, BLY 33, MRF 237, 2N3924
2SC3200	Si-N	NF, ra, 120V, 0,1A, 0,3W, 100MHz	7c	Kec	2SC1775A, 2SC2240, 2SC2362, 2SC2459,++
2SC3201	Si-N	=2SC3200: 0,2W	41c		2SC1775A, 2SC2240, 2SC2362, 2SC2459,++
2SC3202	Si-N	Uni, 35V, 0,5A, 0,3W, 300MHz	7c	Kec	BC 337 33S, BC 635, BC 637, BC 639,++
2SC3203	Si-N	Uni, 35V, 0,8A, 0,6W, 120MHz	7c	Kec	BC 337 33S, BC 635, BC 637, BC 639,++
2SC3204	Si-N	=2SC3203: 0,3W	41c		BC 337..338, BC 635, BC 637, BC 639,++
2SC3205	Si-N	NF-Tr/E, 30V, 2A, 1W, 120MHz	7c(9mm)	Kec	2SC3328, 2SD1014, 2SD1146, 2SD1207,++
2SC3206	Si-N	NF/Vid, 200V, 0,05A, 0,3W, 120MHz	7c(9mm)	Kec	BF 422(A), 2SC3467..69, 2SC3249
2SC3207	Si-N	NF/Vid, 300V, 0,1A, 0,9W, 70MHz	7c(9mm)	Kec	2SC3468..69, 2SC3249, (BF 459, 2SC4019+)
2SC3208	Si-N	S-L, 300/300V, 0,15A, 100MHz	17j	Kec	2SC1505..1507, 2SC1755..1757, 2SC1905
2SC3208	Si-N	CTV-Vid-E, 300/300V, 0,2A, 1W, 50MHz	9b	Nec	BF299, BF 393, BFR69, 2SC3468,++
2SC321	Si-N	HF/S, 40V, 0,2A, 0,36W, 20/25ns, B>30	2a	Hit	BSS 11, BSX1920, 2N2368..69(A),++
2SC3210	Si-N	S-L, 500/400V, 10A, 100W, <1/3,5µs	16c	Mat	2SC4297, 2SC4423
2SC3211	Si-N	S-L, 800/500V, 5A, 70W, <1/4µs	16c	Mat	BUW 11(A)F, 2SC4300, 2SC4457..58
2SC3211A	Si-N	=2SC3211: 900/500V, <1,2/4,2µs	16c		BUW11AF, 2SC4300, 2SC4586
2SC3212	Si-N	S-L, 800/500V, 7A, 100W, <1/3,5µs	16c	Mat	BUV 47(A)FI, BUW 12(A)F, 2SC4301
2SC3212A	Si-N	=2SC3212: 900/500V, <1,2/3,7µs	16c		BUV47AFI, BUW 12AF, 2SC4301
2SC3213	Si-N	S-L, 800/400V, 75A, 300W, <1,5/4,5µs		Org	—
2SC3214	Si-N	S-L, 1200/800V, 5A, 80W	23a	Org	MJ8502..8503, 2SC3080, 2SC3343, 2SC3387
2SC3215	Si-N	S-L, 1200/800V, 10A, 125W, <1/5µs	23a	Org	BUV 48B,C, MJ8504..8505, 2SC3061,++
2SC3216	Si-N	S-L, 1200/800V, 20A, 200W	23a	Org	—
2SC3217	Si-N	DuaL, UHF-L, 50V, 12A, PQ=10W(660MHz)	≈61	Nec	—
2SC3218	Si-N	DuaL, UHF-L, 55V, 15A, PQ=80W(860MHz)	≈61	Nec	—
2SC3219	Si-N	S-L, 230/230V, 8A, 50W, <300/600ns	17j	Shi	BU 409, MJE51T..53T, 2SC2767,++
2SC322	Si-N	=2SC321: B=40	2a	Hit	BSS 11, BSX19..20, 2N2368 69(A),++
2SC3220	Si-N	S-L, 230/230V, 10A, 100W, <300/600ns	16c(j)	Shi	TIP 160..162, 2SC2729, 2SC2944,++
2SC3221	Si-N	S-L, 230/230V, 6A, 80W, <300/600ns	22a	Shi	BU 409, TIP 150..152, 2SC1987, 2SC2767++
2SC3222	Si-N	S-L, 230/230V, 10A, 100W, <300/600ns	23a	Shi	BUX 17(A..C), BUX 42..43, 2SC2944,++
2SC3223	Si-N	S-L, 230/230V, 20A, 200W, <300/600ns	23a	Shi	BUV 11..12, BUW58, BUW73, BUX11..12
2SC3224	Si-N	S-L, 230/230V, 30A, 300W, <300/600ns	68a	Shi	2SC1301, 2SC2249, 2SC2445, 2SC2940,++
2SC3225	Si-N	hi-beta, lo-sat, 40V, 2A, 220MHz, B>500	7c(9mm)	Tos	—
2SC3226	Si-N	NF-Tr/E, 30V, 2A, 0,9W, 150MHz	7c(9mm)	Kec	2SC3328, 2SD1014, 2SD1146, 2SD1207,++
2SC3227	Si-N	NF-Tr/E, 80V, 0,4A, 0,8W, 100MHz	7c(9mm)	Kec	2SC3939, 2SD667(A), 2SD1937, 2SA1211,++
2SC3228	Si-N	NF-Tr/E, 180V, 1A, 0,9W, 120MHz	7c(9mm)	Kec	2SC2363, 2SD1812
2SC3229	Si-N	NF/Vid-L, 300V, 0,05A, 95MHz	13j	Kec	(BF 583, BF 617, BF 759..759, BF 859,++)
2SC323	Si-N	Uni, 40V, 0,1A, 0,25W, 250MHz	2a	Tos	BC 167, BC 183, BC 237, BC 547, 2SD767++
2SC3230	Si-N	NF/S-L, 30V, 3A, 10W, 100MHz	17j	Kec	2SC1173, 2SC2582, 2SC3252..3253,++
2SC3231	Si-N	NF/S-L, 200V, 4A, 40W, 8MHz, <3/9,5µs	17j	Kec	BD243F, 2SC2767, 2SD772A,B
2SC3232	Si-N	S-L, 900/400V, 8A, 80W, <0,5/4µs	16j	Nec	BU426A, BUW11A, 2SC3535, 2SC3796A,++
2SC3233	Si-N	S-L, 500/400V, 2A, 20W, <1/3,5µs	30j	Tos	2SC3631, (BUV93..95)
2SC3234	Si-N	TV-VA-E, 150/150V, 1,5A, 25W, 4MHz	≈15j	Tos	2SC1689, 2SC2073, 2SD608(A), 2SD1136,++
2SC3235	Si-N	S-L, 500/400V, 2A, 20W, <1/3,5µs	≈15j	Tos	BUX 34..35, 2SC2333, 2SC2534, 2SC2736,++
2SC3236	Si-N	S-L, 500/400V, 5A, 60W, <1/3,5µs	≈15j	Tos	BUT 11(A), BUV 46(A), 2SC2827, 2SC3497++
2SC3237	Si-N	NF/S-L, 30V, 3A, 20W, 100MHz	≈15j	Tos	2SC1173, 2SC2562, 2SC3252..3253
2SC3238	Si-N	NF/S-L, 180V, 1,5A, 25W, 100MHz	≈15j	Tos	2SC2236(A,B), 2SC2344, 2SD608(A),++
2SC3239	Si-N	lo-sat, 60V, 5A, 25W, 120MHz	≈15j	Tos	2SC2582, 2SC3253..54, 2SC3258
2SC324	Si-N	HF, 20V, 25mA, 0,2W, 180MHz	2a	Fui	BF 240..241, BF 254..255, BF 594..595,++
2SC3240	Si-N	AM-L, 50V, 25A, PQ=110W(30MHz)	59r	Mit	2SC2879
2SC3241	Si-N	AM-L, 50V, 18A, PQ=85W(30MHz)	59r	Mit	MRF421, MRF454
2SC3242(A)	Si-N	Uni, 20V, 2A, 0,9W, 80MHz	7c(9mm)	Mit	2SC3226, 2SD787..788, 2SD1148, 2SD1207++
2SC3243	Si-N	Uni, 60V, 1A, 0,9W, 120MHz	7c(9mm)	Mit	2SD667, 2SD863, 2SD1207, 2SD1292,++
2SC3244	Si-N	Uni, 100V, 0,5A, 0,9W, 130MHz	7c(9mm)	Mit	2SC1670, 2SC2235, 2SD1211, 2SD1937
2SC3245	Si-N	Uni, 120V, 0,1A, 0,9W, 200MHz	7c(9mm)	Mit	2SC2389, 2SC2459, 2SC2632, 2SC3800,++
2SC3245A	Si-N	=2SC3245: 150V	7c(9mm)		2SC2362K, 2SC2632, 2SC3248, 2SC3800
2SC3246	Si-N	lo-sat, 30V, 1,5A, 0,9W, 130MHz, B>400	7c(9mm)	Mit	2SC3225, 2SC4369
2SC3247	Si-N	lo-sat, 50V, 1A, 0,9W, 130MHz, B>600	7c(9mm)	Mit	(2SC3225)
2SC3248	Si-N	Uni, 180V, 0,1A, 0,9W, 130MHz	7c(9mm)	Mit	BF 422A, 2SC3467..69, 2SC3249

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2SC3249	Si-N	Vid, 300/250V, 0,1A, 0,9W, 30MHz	7c(9mm)	Mit	BF420A, 2SC3468..69, 2SC4168
2SC325	Si-N	UHF, 12V, 0,05A, 0,25W, 1000MHz	5g	Oki	BFR37, BFW30, BFX73, 2SC2570(A), ++
2SC3250	Si-N	Vid-E, 300/300V, 0,1A, 15W, 100MHz	17o(B=case)	Mat	(2SC1505..1507, 2SC1755..1757, 2SC1905)
2SC3251	Si-N	HF-L, 55V, 0,4A, 15W, 700MHz	17i(E=case)	Mat	—
2SC3252	Si-N	NF/S-L, 80V, 3A, 30W, 100MHz	17j	Say	BDV10..12, MJE1502S, 2SC3259
2SC3253	Si-N	NF/S-L, Io-sat, 80V, 5A, 30W, 100MHz	17j	Say	2SC3258
2SC3254	Si-N	NF/S-L, Io-sat, 80V, 7A, 35W, 100MHz	17j	Say	2SC3346
2SC3255	Si-N	NF/S-L, Io-sat, 80V, 10A, 40W, 100MHz	17j	Say	2SC3346
2SC3256	Si-N	NF/S-L, Io-sat, 80V, 15A, 70W, 100MHz	18j	Say	(2SD1238L, 2SD1840)
2SC3257	Si-N	S-L, 250/200V, 10A, 40W, <1/3,5µs	17j	Tos	BUS38..37, BUV27(A), 2SC2687
2SC3258	Si-N	S-L, Io-sat, 100/80V, 5A, 30W, 120MHz	17j	Tos	—
2SC3259	Si-N	S-L, 800/800V, 3A, 40W, B=10	17c	Shi	(BUD46(A))
2SC326	Si-N	UHF, 20V, 0,05A, 0,25W, 1000MHz	5g	Oki	BFR37, BFW30, BFX73, 2SC2570(A), ++
2SC3260	Si-N	=2SC3259: 50W	16c		2SC3472
2SC3261	Si-N	S-L, 800/800V, 6A, 80W, B=10	16c	Shi	—
2SC3262	Si-N	S-L, 800/800V, 10A, 100W, B=10	16c	Shi	(BUT51P)
2SC3263	Si-N	NF/S-L, 230/230V, 15A, 130W, 60MHz	18j	Sak	2SC2944
2SC3264	Si-N	NF/S-L, 230/230V, 17A, 200W, 60MHz	20j	Sak	2SC3438
2SC3265	Si-N	SMD, Uni, Io-sat, 35V, 0,8A, 120MHz	35a	Tos	BCW65..68
2SC3266	Si-N	Uni, 20V, 2A, 0,75W, 120MHz	7c	Tos	MPS650, 2SC3205, 2SC3226, 2SD1207, ++
2SC3267	Si-N	=2SC3266: 0,4W	41c		MPS650, 2SC3205, 2SC3226, 2SD1207, ++
2SC3268	Si-N	SMD, VHF/UHF, 17V, 0,07A, 0,3W, 5GHz	39b	Tos	BFQ19, 2SC3301
2SC3269	Si-N	Vid, 300/300V, 0,1A, 0,75W, 100MHz	7c(9mm)	Rhm	BF420A, 2SC3249, 2SC3468..69, 2SC4168
2SC327	Si-N	UHF, 30V, 0,05A, 0,25W, 1000MHz	5g	Oki	BFR37, BFW30, BFX73, 2SC2570(A), ++
2SC3270	Si-N	=2SC3269: 1W	9c		→2SC3296
2SC3271	Si-N	=2SC3269: 5W	14b		2SC3789..90, 2SC4828
2SC3272	Si-N	=2SC3269: 10W	14h		BF417, BF459, 2SC2621, 2SC3417, ++
2SC3273	Si-N	UHF, 15V, 0,05A, 0,4W, 2,5GHz	7c	Mat	2SC2496, 2SC2570(A), 2SC3037
2SC3274	Si-N	UHF, 15V, 0,05A, 0,4W, 1,3GHz	7c	Mat	BF357, 2SC2498, 2SC2570(A), 2SC3037
2SC3275	Si-N	UHF, 15V, 0,05A, 0,4W, 1,8GHz	7c	Mat	BF357, 2SC2496, 2SC2570(A), 2SC3037
2SC3276	Si-N	UHF, 15V, 0,03A, 0,35W, 7GHz	25p	Mat	BFG65, 2SC1655..1656, 2SC1923
2SC3277	Si-N	S-L, 500/400V, 10A, 90W, 20MHz	18j	Say	BUV47(A), BUW12(A), 2SC3042, 2SC4138++
2SC3278	Si-N	=2SC3277: 100W	23a	Say	BUS12(A), BUW25..26, BUW34..38, ++
2SC3279	Si-N	Uni, Io-sat, 30V, 2A, 0,75W, 150MHz	7c	Tos	MPS650, 2SC3205, 2SC3226, 2SD1207, ++
2SC328	Si-N	UHF, 30V, 0,02A, 0,2W, 1500MHz	5g	Oki	BFR37, BFW30, BFX73, 2SC2570(A), ++
2SC3280	Si-N	HiFi-NF-E, 160/180V, 12A, 120W, 30MHz	77j	Tos	2SC4029, 2SD1704, 2SD1717..18, 2SD2029++
2SC3281	Si-N	HiFi-NF-E, 200/200V, 15A, 150W, 30MHz	77j	Tos	2SC4029
2SC3282(A)	Si-N	UHF-L, 35V, 7,5A, PQ=23W(860MHz)	61v	Nec	BLV95, MRF644
2SC3283(A)	Si-N	UHF-L, 35V, 15A, PQ=37W(860MHz)	61v	Nec	—
2SC3284	Si-N	NF/S-L, 150/150V, 14A, 125W, 80MHz	18j	Sak	2SC2987(A), 2SC3907, 2SD1047, 2SD1703
2SC3285	Si-N	S-L, 1000/800V, 3A, 70W, <1/3µs	18j	Mat	BUW11A, BUW131A, 2SC3534..35, 2SC3152+
2SC3286	Si-N	VHF-L, 55V, 24A, PQ=126W(230MHz)	≈61	Nec	—
2SC3287	Si-N	UHF, 38V, 0,1A, PQ=80mW(915MHz)	25q	Mat	2SC3368
2SC3288	Si-N	UHF, 36V, 0,3A, PQ=0,35W(915MHz)	25q	Mat	2SC3369, 2SC3019
2SC3289	Si-N	UHF-L, 38V, 0,8A, PQ=1,5W(915MHz)		Mat	—
2SC329	Si-N	UHF, 30V, 0,02A, 0,2W, 1500MHz	5g	Oki	BFR37, BFW30, BFX73, 2SC2570(A), ++
2SC3290	Si-N	UHF-L, 38V, 2A, PQ=6,5W(915MHz)		Mat	—
2SC3291	Si-N	UHF-L, 38V, 3A, PQ=17W(915MHz)		Mat	—
2SC3292	Si-N-Darl+Di	S-L, 50V, 1,8A, 20W, 180MHz, B=4000	17c(H)	Say	—
2SC3293	Si-N-Darl+Di	S-L, 50V, 2A, 20W, 180MHz, B=4000	17c(H)	Say	—
2SC3294	Si-N-Darl+Di	S-L, 50V, 5A, 25W, 180MHz, B=4000	17c(H)	Say	—
2SC3295	Si-N	SMD, hi-beta, 50V, 0,15A, 250MHz, B>600	35a	Tos	—
2SC3296	Si-N	TV-VA, NF/S-L, 150V, 1,5A, 20W, 4MHz	17c	Tos	2SC3298(A,B), 2SC3364, 2SC3567, 2SC4159
2SC3297	Si-N	NF/S-L, 30V, 3A, 15W, 100MHz	17c	Tos	2SC3299, 2SD1913
2SC3298	Si-N	NF/S-L, 180V, 1,5A, 20W, 100MHz	17c	Tos	2SC3364, 2SC4159
2SC3298A	Si-N	=2SC3298: 180V	17c		2SC4159
2SC3298B	Si-N	=2SC3298: 200V	17c		—
2SC3299	Si-N	DC-DC-Con., Io-sat, 80V, 5A, 20W, 120MHz	17c	Tos	2SC3746..47
2SC33	Si-N	HF, 45V, 50mA, 250MHz	5g	Nec	BF184..165, BF240..241, BF254..255, ++
2SC330	Si-N	UHF, 20V, 0,02A, 0,2W, 3500MHz	24l	Oki	BFR34, BFT97, BFQ59..60, BFQ70
2SC3300	Si-N	S-L, Io-sat, 100V, 15A, 100W	18j	Sak	2SD1840
2SC3301	Si-N	SMD, UHF, 15V, 0,08A, 7GHz	39b	Tos	2SC3357
2SC3302	Si-N	UHF, 17V, 0,07A, 7GHz	25q	Tos	BFQ73
2SC3303	Si-N	NF/S-L, Io-sat, 100V, 5A, 20W, 120MHz	30j	Tos	—
2SC3304	Si-N	S-L, 250/200V, 10A, 40W, <1/3,5µs	≈15j	Tos	BUS38..37, BUV27(A), 2SC2687
2SC3305	Si-N	S-L, 900/800V, 3A, 40W, <1/5µs	≈15j	Tos	BUT11(A), BUV46(A), 2SC3490..3491, ++

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2SC3306	Si-N	S-L, 500/400V, 10A, 100W, <1/3,5µs	18j	Tos	BUV48(A..C, BUW13(A), 2SC3042, ++
2SC3307	Si-N	S-L, 900/800V, 10A, 150W, <1/4µs	77j	Tos	2SC3910, 2SC3982, 2SC3992
2SC3308	Si-N	S-L, lo-sat, 100V, 5A, 30W, 120MHz	≈15j	Tos	—
2SC3309	Si-N	S-L, 500/400V, 2A, 20W, -/<3,5µs	17c	Tos	BUX84F..85F, 2SC4421, 2SC4533, ++
2SC331	Si-N	UHF, 20V, 0,02A, 0,2W, 3500MHz	24l	Oki	BFR34, BFT97, BFQ59..60, BFQ70
2SC3310	Si-N	S-L, 500/400V, 5A, 30W, -/<3,5µs	17c	Tos	BUT11(A)F, 2SC3497, 2SC4073, 2SC4371, ++
2SC3311	Si-N	Uni, 30V, 0,1A, 0,3W, 150MHz	40c	Mat	BC168, BC183, BC238, BC548, ++
2SC3311A	Si-N	=2SC3311: 60V	40c		BC167, BC182, BC237, BC547, ++
2SC3312	Si-N	Uni, ra, 60V, 0,1A, 0,3W, 200MHz	40c	Mat	BC414, BC550, 2SC1775(A), 2SC2390, ++
2SC3313	Si-N	AM/FM, 30V, 0,03A, 0,3W, 250MHz	40c	Mat	BF240..241, BF254..255, BF594..595, ++
2SC3314	Si-N	AM/FM, 30V, 0,03A, 0,3W, 300MHz	40c	Mat	BF198..199, BF224..225, BF596..597, ++
2SC3315	Si-N	AM/FM, 30V, 15mA, 0,3W, 650MHz	40c	Mat	BF225, BF314, BF502, BF605, BF507++
2SC3316	Si-N	S-L, 500/400V, 2A, 40W, <500/1650ns	17j	Fjd	BUX84..85, 2SC2333, 2SC2534, 2SC2738, ++
2SC3317	Si-N	S-L 500/400V, 5A, 40W, <500/1650ns	17j	Fjd	BUT11(A), BUV46(A), 2SC2827, 2SC3497++
2SC3318	Si-N	S-L, 500/400V, 10A, 80W, <500/1650ns	18j	Fjd	BUV47(A), BUW12(A), 2SC2828, 2SC3042++
2SC3319	Si-N	S-L, 500/400V, 10A, 100W, <500/1650ns	23a	Fjd	BUW25..26, BUW34..38, 2SC3046, ++
2SC332	Si-N	HF/S, 30V, 0,2A, 0,15W, 450MHz	5g	Oki	BSS11, BSX19..20, 2N2368..69(A), ++
2SC3320	Si-N	S-L, 500/400V, 15A, 80W, <500/1650ns	18j	Fjd	BUV48(AC), BUW13(A), 2SC3520, ++
2SC3321	Si-N	S-L, 500/400V, 15A, 100W, <500/1650ns	23a	Fjd	BUV25, BUW44, BUX25, 2SD641, ++
2SC3322	Si-N	S-L, 900/800V, 5A, 80W, <1/4µs	18j	Hit	BUW11A, 2SC3153, 2SC3232, 2SC3535, ++
2SC3323	Si-N	SMD, NF, ra, 60V, 0,15A, 150MHz	35a	Tos	BC846, BCV71..72, 2SC1682A, 2SC3324
2SC3324	Si-N	SMD, NF, ra, 120V, 0,1A, 100MHz	35a	Tos	2SD614
2SC3325	Si-N	SMD, Uni, 50V, 0,5A, 300MHz	35a	Tos	BC817, BCX19, 2SC3441
2SC3326	Si-N	SMD, hi-Ueb, 50V, 0,3A, 30MHz	35a	Tos	2SC3134
2SC3327	Si-N	=2SC3326:	41c		2SC2678
2SC3328	Si-N	Uni, lo-sat, 60V, 2A, 0,9W, 100MHz	7c(9mm)	Tos	2SC4489, 2SD2182
2SC3329	Si-N	NF, ra, 60V, 0,1A, 0,4W, 42MHz	7c	Tos	2SC1775(A), 2SC2240, 2SC2390, 2SC2459, ++
2SC333	Si-N	=2SC322: 40V	5g	Oki	BSS11, BSX19..20, 2N2368..69(A), ++
2SC3330	Si-N	Uni, 60V, 0,2A, 0,3W, 200MHz	40c	Say	BC174, BC182, BC190, BC546, ++
2SC3331	Si-N	=2SC3330: 0,5W	7c		BC174, BC182, BC190, BC546, ++
2SC3332	Si-N	Uni, 160V, 0,7A, 0,7W, 120MHz	7c	Say	2SC4612
2SC3333	Si-N	S, Vid, 250V, 0,05A, 0,6W, 100MHz	7c	Tos	BF298..299, BF422, 2SC3468, ++
2SC3334	Si-N	=2SC3333: 0,9W	7c(9mm)		BF422(A), 2SC3249, 2SC3467..69
2SC3335	Si-N	=2SC3333: 5W	14h		BF415, BF417, BF458..459, BF471, ++
2SC3336	Si-N	S-L, 500/400V, 15A, 100W, <0,5/2µs	18j	Hit	BUV48(AC), BUW13(A), 2SC3520, ++
2SC3337	Si-N	VHF/UHF, 20V, 0,1A, 0,6W, 4,4GHz	7l	Hit	2SC2570(A), 2SC3037, 2SC3605
2SC3338	Si-N	SMD, UHF, 15V, 0,05A, 4,5GHz	39b	Hit	BFQ19, 2SC3268
2SC3339	Si-N	SMD, Uni, 60V, 0,15A, >80MHz	35d	Tos	BC846R..847R, BCV71R..72R
2SC334	Si-N	=2SC322: 60V	5g	Oki	2N4014
2SC3340	Si-N	SMD, Uni, 120V, 0,1A, 100MHz	35d	Tos	(2SC1822A, 2SC3324)
2SC3341	Si-N	SMD, Uni, 35V, 0,5A, 300MHz	35d	Tos	BC817R, BCW65R, BCX19R, (2SC3325)
2SC3342	Si-N	S-L, TV-HA, 1300/500V, 5A, 50W	23a	Hit	BU207..209(A), BU508(A), MJ8503, ++
2SC3343	Si-N	S-L, TV-HA, 1200/500V, 5A, 50W	23a	Hit	BU207..209(A), BU508(A), MJ6503, ++
2SC3344	Si-N	S-L, 500/400V, 8A, 60W, -/<3,5µs	≈15j	Tos	BUT56(A), 2SC3562, 2SC4106..07, ++
2SC3345	Si-N	DC-DC-Con., lo-sat, 60V, 12A, 40W, 90MHz	17j	Tos	2SD1212
2SC3346	Si-N	=2SC3345: 80V, 80MHz	17j		—
2SC3347	Si-N	UHF-L, 45V, 2,4A, PO=5,6W(2,2GHz)	62a	Nec	—
2SC3348	Si-N	UHF-L, 45V, 3,6A, PO=11,2W(2,2GHz)	62a	Nec	—
2SC3349	Si-N	UHF-L, 45V, 0,6A, PO=1W(2GHz)	62d	Nec	—
2SC335	Si-N	=2SC322: 50V, 0,25W	2a	Oki	2N4014
2SC3350	Si-N	UHF-L, 45V, 1,2A, PO=3,2W(3GHz)	62a	Nec	—
2SC3351	Si-N	UHF-L, 45V, 2,4A, PO=5,4W(3GHz)	62a	Nec	—
2SC3352	Si-N	S-L, 800/500V, 1,5A, 25W, <1/4µs	17c	Mat	BUX84F..85F, 2SC3352, 2SC3794, 2SD1571+
2SC3352A	Si-N	=2SC3352: 900/500V, <1,2/7,2µs	17c		BUX85F, 2SC3794A, 2SC3978, 2SC4304, ++
2SC3353	Si-N	S-L, 800/500V, 5A, 40W, <1/4µs	17c	Mat	BUT11(A)F, 2SC3750, 2SC3795, 2SC4518
2SC3353A	Si-N	=2SC3353: 900/500V, <1,2/7,2µs	17c		BUT11AF, 2SC3795A, 2SC4518
2SC3354	Si-N	FM/VHF, 30V, 0,05A, 0,3W, 1200MHz	40c	Mat	BF377..378, BF357, 2SC2570, 2SC3037, ++
2SC3355	Si-N	UHF, 20V, 0,1A, 0,6W, 6,5GHz	7l	Nec	—
2SC3356	Si-N	UHF, 20V, 0,1A, 0,2W, 7GHz	35a	Nec	—
2SC3357	Si-N	UHF, 20V, 0,1A, 6,5GHz	39b	Nec	—
2SC3358	Si-N	UHF, 20V, 0,1A, 7GHz	25q	Nec	—
2SC3359(S)	Si-N	Uni, 60V, 0,3A, 0,4W, 150MHz	7c, 41c	Rhm	BC639, 2SC4414, 2SD667, 2SD1226, ++
2SC338	Si-N	=2SC322: 60V, 0,25W	2a	Oki	2N4014
2SC3360	Si-N	SMD, NF/S, 200V, 0,1A, <800/1800ns	35a	Nec	BFN24, BFN26
2SC3361	Si-N	SMD, S, 60V, 0,15A, 120/390ns	35a	Say	BC846, BCV71..72, BSR17, 2SC3392, ++
2SC3362	Si-N	S-L, 500/400V, 1,5A, 10W, <1/3µs	30j	Hit	2SC3233, 2SC3631, (BUV63, BUV93..95)

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2SC3363	Si-N	S-L, 800/500V, 1A, 10W, <1/4µs	30j	Hit	(BUV94..95)
2SC3364	Si-N	NF/S-L, 160V, 1,5A, 20W, 200MHz	17c	Tos	2SC3298(A,B), 2SC4159
2SC3365	Si-N	S-L, 500/400V, 10A, 80W, <1/3,5µs	18j	Hit	BUV47(A), BUW12(A), 2SC3042, 2SC4138++
2SC3366	Si-N	NF/S-L, 150/100V, 5A, 40W, <1/3,5µs	17j	Hit	BD243D, 2SC2518, 2SD772(A,B), ++
2SC3367	Si-N	NF/S-L, 120/80V, 5A, 40W, 300/900ns	17j	Hit	BD243C, BD539D, BD955, 2SD961, ++
2SC3368	Si-N	UHF, 38V, 0,1A, 0,5W, 2,5GHz	25q	Mat	—
2SC3369	Si-N	UHF, 38V, 0,3A, 1W, 3GHz	25q	Mat	2SC3288, 2SC3019
2SC337	Si-N	Uni, 20V, 0,02A, 0,38W, 100MHz	2a	Oki	BC188, BC183, BC238, BC548, 2SD767++
2SC3370	Si-N	NF/S-L, 200V, 15A, 150W, 30MHz	20j	Tos	2SC2773..2774, 2SC3264, 2SD846
2SC3371	Si-N	S-L, 800/500V, 10A, 200W, <1/4µs	23a	Mat	BUS13(A), BUW45..46, BUX48(A..C), ++
2SC3372	Si-N	UHF-L, 38V, 3A, PQ=8W(915MHz)	58v	Mat	—
2SC3373	Si-N	UHF-O, 30V, 0,2A, 0,2W, 1500MHz	24b	Nec	BF383, BFW92..93
2SC3374	Si-N	SMD, VHF, TV-Tuner, 20V, 0,02A, 550MHz	35a	Hit	BF599, BF799, BFS20, 2SC3015, ++
2SC3375	Si-N	Uni, 30V, 0,8A, 0,6W, 120MHz	7c	Tos	BC337..338, BC635, BC637, BC639, ++
2SC3376	Si-N	S-L, 900/800V, 3A, 60W, <-/5µs	18j	Tos	BUW11A, 2SC3152, 2SC3285, 2SC3550, ++
2SC3377	Si-N	Uni, 40V, 1A, 0,5W, 150MHz	7c	Rhm	BC337, BC635, BC637, BC639, ++
2SC3378	Si-N	NF, ra, 120V, 0,1A, 0,2W, 100MHz	41c	Tos	2SC1775A, 2SC2240, 2SC2399, 2SC2459, ++
2SC3379	Si-N	UHF-L, 20V, 1,5A, PQ=3W(520MHz)		Mit	—
2SC336	Si-N	=2SC337: 70V	2a	Oki	BC174, BC182, BC190, BC548, 2SC1890+
2SC3380	Si-N	SMD, Vid, 300V, 0,1A, 30MHz	38b	Hit	BFN18, 2SC3515, 2SC3554
2SC3361	Si-N	Dual, ra, 80V, 0,1A, 0,4W, 170MHz	7-SIP	Tos	—
2SC3362	Si-N	=2SC3363: ra	7c	Say	2SC1775(A), 2SC2240, 2SC2390, 2SC2459, ++
2SC3363	Si-N	Uni, 60V, 0,2A, 0,5W, 250MHz	7c	Say	BC174, BC182, BC190, BC548, ++
2SC3384	Si-N	S-L, 500/400V, 15A, 120W, -/<2µs	23a	Tos	BUV25, BUW44..46, BUX25, 2SD641, ++
2SC3385	Si-N	S-L, 500/400V, 15A, 120W, -/1,5µs	23a	Tos	BUV25, BUW44..46, BUX25, 2SD841, ++
2SC3366	Si-N	NF/S-L, 80/50V, 3A, 10W, <1/3µs	30j	Hit	2SC3303, 2SC4332
2SC3387	Si-N	S-L, 1200/500V, 5A, 50W, <1/7µs	18j	Hit	BU508(A), BU903, BU908, 2SC3642, ++
2SC3368	Si-N	S-L, 1200/500V, 5A, 50W, <1/6µs	23a	Hit	BU207..209, BU508(A), 2SD1099, 2SD1103
2SC3369	Si-N	Uni, 20V, 2A, 0,7W, 80MHz	7c	Mit	2SC3205, 2SC3225, 2SC3226, 2SD787..788++
2SC339	Si-N	=2SC337: 110V	2a	Oki	2SC1775A, 2SC1845, 2SC2240, 2SC3245, ++
2SC3390	Si-N	Uni, ra, 55V, 0,1A, 0,3W, 200MHz	41c	Hit	BF240..241, BF254..255, BF959, ++
2SC3391	Si-N	VHF, 30V, 0,02A, 0,2W, 940MHz	41c	Hit	BF377..378, BF689, BF783, 2N2857, ++
2SC3392	Si-N	=2SC3393: SMD	35a	Say	BSR14, BSS79, BSS81
2SC3393	Si-N	S, 60V, 0,5A, 0,3W, 70/470ns	40c	Say	BSV59, BSX49, 2N3301..02, 2N2221..22++
2SC3394	Si-N	Uni, 55V, 0,1A, 0,5W, 230MHz	9c	Hit	BC167, BC182, BC237, BC547, ++
2SC3395	Si-N+R	=2SC3399: SMD	35a		KSR1104
2SC3396	Si-N+R	=2SC3400: SMD	35a		KSR1103
2SC3397	Si-N+R	=2SC3401: SMD	35a		KSR1108
2SC3398	Si-N+R	=2SC3402: SMD	35a		KSR1102
2SC3399	Si-N+R	S, Rb=Rbe=47kΩ, 50V, 0,1A, 250MHz	40c	Say	AA1L4M, DTC144ES, RN1004, UN4213, ++
2SC34	Ge-N	NF/S, 20V, 0,25A, 0,14W, 6MHz	1a	Mat	AC127, ASY28..29, ASY73..75
2SC340	Si-N	Mm, Uni, 20V, 0,02A, 0,1W, 130MHz	24c	Oki	(BC188, BC183, BC238, BC548, 2SD767)
2SC3400	Si-N+R	S, Rb=Rbe=22kΩ, 50V, 0,1A, 250MHz	40c	Say	AA1F4M, DTC124ES, RN1003, UN4212, ++
2SC3401	Si-N+R	S, Rb=46kΩ, Rbe=23kΩ, 50V, 0,1A, 250MHz	40c	Say	AA1L4L, DTC144WS, RN1009, UN421E, ++
2SC3402	Si-N+R	S, Rb=Rbe=10kΩ, 50V, 0,1A, 250MHz	40c	Say	AA1A4M, DTC114ES, RN1002, UN4211, ++
2SC3403	Si-N	S-L, 500/400V, 2A, 25W, <1/4µs	30j	Mat	2SC4219, 2SC4597, 2SC4754
2SC3404	Si-N	VHF-Tr/E, 20V, 1A, PQ=1,7W(175MHz)		Mit	—
2SC3405	Si-N	S-L, 900/800V, 0,8A, 20W, <1/5µs	30j	Tos	2SC3489, (BUV95, BUX85, 2SC3149, ++)
2SC3406	Si-N	UHF-L, 38V, 3A, PQ=8W(915MHz)		Mat	—
2SC3407	Si-N	UHF-L, 38V, 2A, PQ=3,5W(915MHz)			—
2SC3408	Si-N	NF/Vid, 300V, 0,1A, 10W, 60MHz	30j	Mat	2SC2870, 2SC2924, 2SC3805, 2SC4019, ++
2SC3409	Si-N	S-L, 900/800V, 2A, 60W, <1/4,8µs	18j	Sak	BUW11A, 2SC3152, 2SC3376, 2SC3550, ++
2SC341	Si-N	=2SC340: 70V	24c	Oki	(BC174, BC182, BC546, 2SC1390, ++)
2SC3410	Si-N	UHF-L, 35V, 2A, PQ=7,2W(500MHz)	55s	Nec	—
2SC3411	Si-N	S-L, 800/400V, 10A, 50W, <1/4,5µs	23a	Hit	BUS12(A), BUW28, BUW35..39, 2SC3049++
2SC3412	Si-N	S-L, TV-HA, 1200/500V, 8A, 50W, <1/4,5µs	23a	Hit, Tho	BU137A, MJ8504..8505, 2SC3215, ++
2SC3413	Si-N	Uni, 40V, 0,1A, 0,3W, 200MHz	41c	Hit	BC167, BC182, BC237, BC547, ++
2SC3414	Si-N	=2SC3413: 0,4W	9c		BC167, BC182, BC237, BC547, ++
2SC3415	Si-N	=2SC3269: 0,5W	7c	Rhm	BF299, BF393, BF420A, 2SC3468, ++
2SC3416	Si-N	Vid, hi-def, 200V, 0,1A, 5W, 70MHz	14h	Say	2SC3502..03, (BF415, BF417, ++)
2SC3417	Si-N	=2SC3416: 300V	14h		2SC3503, (BF417)
2SC3418	Si-N	=2SC3416: 400V, 100MHz	14h		(BF850)
2SC3419	Si-N	lo-sat, 40V, 0,8A, 5W, 100MHz	14b	Tos	2SD1684, (BD135, BD228, BD375)
2SC342	Si-N	=2SC340: 110V	24c	Oki	(2SC1775A, 2SC1845, 2SC2240, 2SC3245, ++)
2SC3420	Si-N	lo-sat, 50V, 5A, 10W, 100MHz	14b	Tos	2SD1885, (2SC2270, 2SD826)
2SC3421	Si-N	NF/HF/S-L, 120V, 1A, 10W, 120MHz	14b	Tos	2SC3621, 2SD1361, 2SD1684

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2SC 3422	Si-N	NF/HF/S-L, 40V, 3A, 10W, 100MHz	14b	Tos	2SD1683, 2SD1685, (BD785, MJE240..242)
2SC 3423	Si-N	NF-L, 150V, 0,05A, 5W, 200MHz	14b	Tos	2SC3787..88, 2SC3956, (BF415, BF469++)
2SC 3424	Si-N	S/Vid-L, 250V, 0,05A, 80MHz	14b	Tos	2SC3789..90, (BF415, BF417, BF469,++)
2SC 3425	Si-N	S-L, 500/400V, 0,8A, 10W, -/<4µs	14b	Tos	(BD410, 2SC3051)
2SC 3426	Si-N	SMD, Uni, lo-sat, 15V, 0,8A, 120MHz	35a	Tos	BCW65..68, 2SC3265
2SC 3427	Si-N	NF/S-L, 50V, 7A, 50W, <200/2300ns	17j	Shi	BD543A, BD797, BD805
2SC 3426	Si-N	NF/S-L, 80V, 10A, 50W, <200/2300ns	17j	Shi	BD707, BD743A, BD807
2SC 3429	Si-N	SMD, UHF, 17V, 0,07A, 5GHz	35a	Tos	2SC3161
2SC 343	Si-N	HF/S, 35V, 0,5A, 0,6W, 430MHz	2a	Oki	BSV69, 2N3722..25, 2SC1072, 2SC1395, ++
2SC 3430	Si-N	S-L, 500/400V, 2A, 20W, <0,5/1,8µs	15j	Nec	BUX84..85, 2SC2333, 2SC2534, 2SC2738, ++
2SC 3431	Si-N	S-L, 500/400V, 5A, 40W, <0,5/1,8µs	15j	Nec	BUT11(A), BUV46(A), 2SC2827, 2SC3497++
2SC 3432	Si-N	S-L, 500/400V, 7A, 80W, <0,5/1,8µs	15j	Nec	BUT56(A), 2SC3039, 2SC3170, 2SC4106, ++
2SC 3433	Si-N	S-L, 500/400V, 10A, 60W, <0,5/1,8µs	15j	Nec	BUV56(A), BUV68(A), 2SC3562, ++
2SC 3434	Si-N	S-L, 500/400V, 10A, 100W, <0,5/1,8µs	16j	Nec	BUV47(A), BUW12(A), 2SC2828, 2SC3042++
2SC 3435	Si-N	S-L, 500/400V, 15A, 120W, <0,5/1,8µs	16j	Nec	BUV48(A), BUW13(A), 2SC4139..40, ++
2SC 3438	Si-N	S-L, 500/500V, 20A, 200W, <1/1,7µs	20j	Nec	—
2SC 3437	Si-N	SMD, HF/S, 40V, 0,2A, 70/45ns	35a	Tos	BSR17, 2SC3392
2SC 3438	Si-N	SMD, Uni, 100V, 0,5A, 130MHz	39b	Mit	2SC2681, 2SD968(A), 2SD1006..1007
2SC 3439	Si-N	SMD, lo-sat, 30V, 1,5A, 130MHz, B>400	39b	Mit	(2SC2982, 2SD1621)
2SC 344	Si-N	=2SC343: 80V	2a	Oki	BSV77, 2N3722..23, 2SC1072, 2SC1385, ++
2SC 3440	Si-N	SMD, Uni, 25V, 0,7A, 180MHz	35a	Mit	BCW65..68
2SC 3441	Si-N	SMD, Uni, 55V, 0,4A, 150MHz	35a	Mit	BCW85..68, BCX41
2SC 3442	Si-N	Uni, 50V, 0,1A, 0,3W, 100MHz	41c	Mit	BC167, BC162, BC237, BC547, ++
2SC 3443	Si-N	SMD, lo-sat, 20V, 2A, 80MHz	39b	Mit	2SC2982, 2SC3439, 2SD1621
2SC 3444	Si-N	SMD, lo-sat, 80V, 1A, 80MHz	39b	Mit	2SC4409, 2SD1622..1623
2SC 3445	Si-N	SMD, UHF, 15V, 0,08A, 7GHz	35a	Tos	2SC3356
2SC 3446	Si-N	S-L, 800/500V, 3A, 50W, <0,5/3,3µs	17j	Say	BUT11(A), BUV46(A), 2SC3047, 2SC3087++
2SC 3447	Si-N	S-L, 800/500V, 5A, 50W, <0,5/3,3µs	17j	Sey	BUT11(A), BUV46(A), 2SC3087, 2SC3353++
2SC 3448	Si-N	S-L, 800/500V, 4A, 60W, <0,5/3,3µs	18j	Say	BUW11(A), BUW131(A), 2SC3088, 2SC3796+
2SC 3449	Si-N	S-L, 800/500V, 7A, 80W, <0.5/3,3µs	18j	Say	BU426(A), BU926, 2SC3089, 2SC3538, ++
2SC 345	Si-N	=2SC343: 80V	2a	Oki	BSV95, 2N3722..23, 2N3725, 2N3735
2SC 3450	Si-N	S-L, 800/500V, 10A, 90W, <0,5/3,3µs	18j	Say	BUV47(A), BUW12(A), 2SC3090, 2SC3637++
2SC 3451	Si-N	S-L, 800/500V, 15A, 100W, <0,5/3.3µs	18j	Say	BUV46(A..C), BUW13(A), 2SC3552
2SC 3452	Si-N	S-L, 800/500V, 7A, 70W, <0,5/3,3µs	23a	Say	BU326(A), BU426(A), BUX47(A), ++
2SC 3453	Si-N	S-L, 800/500V, 10A, 100W, <0,5/3,3µs	23a	Say	BUS12(A), BUW26, BUW34..35, 2SC3049++
2SC 3454	Si-N	S-L, 800/500V, 15A, 120W, <0,5/3,3µs	23a	Say	BUS13(A), BUW45..46, BUX48(A..C), ++
2SC 3455	Si-N	S-L, 800/500V, 25A, 160W, <0.5/3,3µs	23a	Say	BUS14(A), BUS98(A)
2SC 3456	Si-N	S-L, 1100/800V, 1,5A, 40W, <0,5/3,3µs	17j	Say	MJE8500..8501, 2SC3178, 2SC4230
2SC 3457	Si-N	S-L, 1100/800V, 3A, 50W, <0,5/3,3µs	17j	Say	MJE8502..8503, 2SC3050
2SC 3458	Si-N	S-L, 1100/800V, 3A, 80W, <0,5/3,3µs	18j	Say	2SC3387, 2SC3842
2SC 3459	Si-N	S-L, 1100/800V, 4,5A, 90W, <0,5/3,3µs	18j	Say	2SC3387, 2SC3642
2SC 346	Si-N	HF/S, 45V, 0,7A, 0,6W, <80/70ns	2a	Oki	BSV68, 2N3722..25, 2SC1072, 2SC1385, ++
2SC 3460	Si-N	S-L, 1100/800V, 6A, 100W, <0,5/3,3µs	18j	Say	BU902..903, 2SC3643
2SC 3461	Si-N	S-L, 1100/800V, 8A, 140W, <0,5/3,3µs	18j	Say	BU802, 2SC3843
2SC 3462	Si-N	S-L, 1100/800V, 4,5A, 100W, <0,5/3,3µs	23a	Say	BU548, MJ8502..8503, 2SC3343..3344, ++
2SC 3463	Si-N	S-L, 1100/800V, 6A, 120W, <0,5/3,3µs	23a	Say	BU546, MJ8502..8503, 3SC3343..3344, ++
2SC 3464	Si-N	S-L, 1100/800V, 8A, 130W, <0,5/3,3µs	23a	Say	BU536, MJ8504..8505, 2SC3412, ++
2SC 3465	Si-N	S-L, 1100/800V, 12A, 160W, <0,5/3,3µs	23a	Say	BUX48B,C
2SC 3468	Si-N	S-L, 1200/650V, 8A, 120W, <1/4,7µs	18j	Say	MJ8504..05, 2SC3061, 2SC3215, 2SC4285
2SC 3467	Si-N	Vid, hi-def, 200V, 0,1A, 1W, 150MHz	7c(9mm)	Say	(BF420A)
2SC 3468	Si-N	=2SC3467: 300V	7c(9mm)		(BF420A)
2SC 3469	Si-N	=2SC3467: 400V	7c(9mm)		(2SC4168, 2SC2267, 2SD1385)
2SC 347	Si-N	=2SC346: 80V	2a	Oki	BSV77, 2N3722..23, 2SC1072, 2SC1385, ++
2SC 3470	Si-N	Uni, 55V, 0,1A, 0,3W, 230MHz	41c	Hit	BC237, BC547, BF240..41, BF254..55++
2SC 3471	Si-N	Uni, 80V, 0,2A, 0,4W, 250MHz	7b	Hit	BC174, BC162, BC190, BC546, ++
2SC 3472	Si-N-Darl	S-L, 900/650V, 3A, 50W, B=20, <1/5,5µs	18j	Fjd	BUT50P, 2SC3030, 2SC3032
2SC 3473	Si-N	NF/S-L, 50V, 4A, 40W, 50MHz	17j	Hit	2SC2562, 2SC3253, (BD243A, BD535,++)
2SC 3474	Si-N	hi-beta, lo-sat, 80V, 2A, 85MHz, B>500	80j	Tos	—
2SC 3475	Si-N	NF/S-L, lo-sat, 100V, 4A, 20W, 20MHz	17c	Tos	2SC3540, 2SD1411
2SC 3476	Si-N	UHF-L, 35V, 1,5A, PQ=3,5W(520MHz)		Mit	—
2SC 3477	Si-N	UHF, 15V, 0,03A, 0,35W, 4,5GHz	25q	Mat	BFQ71..72, 2SC1119, 2SC1339
2SC 3478(A)	Si-N	S/Vid, 200V, 0,1A, 0,75W, 160MHz	7c	Nec	BF298..299, BF422, 2SC3467..3468, ++
2SC 3479	Si-N+Di+Rbe≈50	TV-HA, hi-def, 1500/800V, 2,5A, 80W	16c	Say	(BU705D, 2SD1290..91, 2SD1728, 2SD1876
2SC 348	Si-N	=2SC346: 80V	2a	Oki	BSV77, 2N3722..23, 2SC1072, 2SC1385, ++
2SC 3480	Si-N+Di	=2SC3479: 3,5A	18j		(BU706D, 2SD1729, 2SD1877)
2SC 3481	Si-N+Di+Rbe≈50	TV-HA, hi-def, 1500/800V, 5A, 120W	16c	Say	2SC3681, (BU508D, 2SD1730, 2SD1878)

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2SC3482	Si-N+Di	=2SC3481: 6A	18j		2SC3681, (BU508D, 2SD1731, 2SD1879)
2SC3483	Si-N	TV-HA, hi-def, 1500V, 2,5A, 80W	77c		(BU508(A), BU705, 2SD1493..1494,++)
2SC3484	Si-N	=2SC3483: 3,5A	18j		(BU508(A), BU706, 2SC3484, 2SD1495)
2SC3485	Si-N	TV-HA, hi-def, 1500/800V, 5A, 120W	77c		2SC3685, (BU508(A), 2SD1496..97)
2SC3486	Si-N	=2SC3485: 6A	18j		2SC3685..86, (BU508(A), 2SD1486..1497)
2SC3487	Si-N	Uni, 50V, 0,1A, 0,3W, 150MHz	7c	Tos	BC187, BC182, BC237, BC547,++
2SC3486	Si-N	Uni, 35V, 0,5A, 0,3W, 300MHz	41c	Tos	BC337..338, BC635, BC637, BC639,++
2SC3489	Si-N	S-L, 900/800V, 0,6A, 10W, <1/1,7µs	30j	Hit	2SC3405, (BUV95, BUX85, 2SC3149,++)
2SC349	Si-N	=2SC348: 90V	2a	Oki	BSV95, 2N3722..23, 2N3625, 2N3735
2SC3490	Si-N	S-L, 900/800V, 3A, 40W, <0,5/3µs	17j	Hit	BUT11(A), BUV46(A), 2SC3148, 2SC3150
2SC3491	Si-N	S-L, 1000/400V, 4A, 80W, <0,75µs	17j	Hit	BUT11(A), BUV46(A), 2SC3148, 2SC3150
2SC3492	Si-N	NF/S-L, 50V, 4A, 40W, 50MHz	17j	Hit	2SC2562, 2SC3253, (BD243, BD535,++)
2SC3493	Si-N	SMD, VHF, TV-Tuner, 15V, 20mA, >700MHz	35a	Hit	BF599, BF799, BFS17, BFS20,++
2SC3494	Si-N	FM-HF/ZF, 30V, 0,1A, 0,3W	41c	Hit	BF240..41, BF254..55, BF594..595,++
2SC3495	Si-N	hi-Ueb, hi-beta, 120V, 0,05A, B=1000	7c	Say	2SC3071
2SC3496(A)	Si-N	S-L, 900V, 1A, 30W, <1/4µs	30j	Mat	2SC4223, 2SC4801, (BUV95, BUX85,++)
2SC3497	Si-N	S-L, 500/400V, 6A, 30W, -/<1,8µs	17c	Tos	BUT16(A)F, 2SC3670, 2SC4130, 2SC4161
2SC3498	Si-N	S-L, 500/400V, 30A, 150W, -/<3µs	77j	Tos	—
2SC3499	Si-N	S-L, 500/450V, 30A, 150W	77j		—
2SC35	Ge-N	NF/S, 20V, 0,4A, 0,14W, 12MHz	1a	Mat	AC127, ASY73..75
2SC350	Si-N	Uni, ra, 30V, 0,1A, 0,2W, 180MHz	2a	Hit	BC169, BC184, BC239, BC549, 2SC2675+
2SC3500	Si-N	UHF-L, 50V, 4A, PQ=4,8W(860MHz)	61r	Nec	—
2SC3501	Si-N	VHF-M/O, TV-Tuner, 20V, 0,05A, 3,5GHz	24b	Hit	BFT85
2SC3502	Si-N	Vid-L, hi-def, 200V, 0,1A, 7W, 150MHz	14h	Say	2SC3418..17, (BF415, BF417, BF469)
2SC3503	Si-N	=2SC3502: 300V	14h		2SC3417..18, (BF417, BF471)
2SC3504	Si-N	CRT, hi-def, 70V, 0,05A, 0,9W, 500MHz	7c(9mm)	Say	2SC3596
2SC3505	Si-N	S-L, 900/700V, 6A, 80W, <1/6µs	18j	Fjd	BUW11A, 2SC3153, 2SC3232, 2SC3535,++
2SC3508	Si-N	S-L, SMPS, 1000/800V, 3A, 70W, <1/3µs	16c	Mat	BUW11AF, 2SC4428..27, 2SC4583..84
2SC3507	Si-N	S-L, SMPS, 1000/800V, 5A, 80W, <1/3µs	18c	Mat	BUW11AF, 2SC4427..28, 2SC4584
2SC3508	Si-N-Darl	B2→B1-Diode, 900/800V, 8A, 80W, B>7	16c	Mat	—
2SC3509	Si-N-Darl	B2→B1-Diode, 900/800V, 10A, 100W, B>7	16c	Mat	—
2SC351	Si-N	HF, 40V, 0,02A, 0,2W, 800MHz	7c	Tos	BF196..199, BF224..225, BF505,++
2SC3510	Si-N	UHF, 20V, 0,05A, 0,6W, 4,5GHz	7l	Hit	2SC2570(A), 2SC3037, 2SC3337, 2SC3512
2SC3511	Si-N	UHF, 15V, 0,05A, 0,2W, 8GHz	25q	Hit	BFG65, BFP91, BFQ66
2SC3512	Si-N	VHF/UHF, 15V, 0,1A, 0,6W, 8GHz	7f	Hit	2SC3355
2SC3513	Si-N	=2SC3512: SMD	35a	Hit	2SC3445
2SC3514	Si-N	NF-L, 180/180V, 0,1A, 10W, 200MHz	17j	Nec	2SC3782, (BF615, BF858..859, BF757++)
2SC3515	Si-N	SMD, Vid, 300/300V, 0,1A, 80MHz	39b	Tos	BFN18, 2SC3380, 2SC3554, 2SC4189
2SC3518	Si-N	S-L, 1200/800V, 30A, 200W	≈74	Drg	—
2SC3517	Si-N	S-L, 1200/800V, 50A, 300W	≈74	Org	—
2SC3518	Si-N	NF/S-L, 80V, 5A, 10W, <1/3µs	30j	Nec	2SC3074, 2SC3303, 2SC3592, 2SD1803,++
2SC3519	Si-N	NF/S-L, 180V, 15A, 130W, 50MHz	18j	Sak	2SC2987A, 2SC3263, 2SD1047, 2SD1703
2SC3519A	Si-N	=2SC3519: 180V	18j		2SC3263, 2SC3907, 2SC3856
2SC352(A)	Si-N	HF/S, 50V, 0,1A, 0,75W, 140MHz	2a	Son	BSY58, 2N2218..19(A), 2N3299..3300,++
2SC3520	Si-N	S-Reg, 500/400V, 16A, 130W, <0,7/3,7µs	18j	Sak	2SC3650, 2SC4110, 2SC4140
2SC3521	Si-N	SMD, S, 40V, 0,1A, <100/150ns	35a	Hit	BSR17, 2SC3381, 2SC3578
2SC3522	Si-N	S-L, 500/400V, 7A, 40W, <1/3,5µs	17j	old	BUT56(A), 2SC3039, 2SC3170, 2SC4106,++
2SC3523	Si-N	NF/S-L, 100V, 3A, 40W	17j	old	BD241C, BD712, BD937, BDV10..12,++
2SC3524	Si-N	NF/S-L, 150V, 7A, 40W, <0,5/2µs	17j	old	BD243D, MJE15030, 2SC4329
2SC3525	Si-N	S-L, 500/400V, 5A, 100W, <1/3µs	23a	old	BUW11(A), BUX45, TIP59A, 2SC3063,++
2SC3526(H)	Si-N	Display-Vid, 110V, 0,15A, 1W, 350MHz	7c(9mm)	Mat	(2SC4708)
2SC3527	Si-N	S-L, 500/400V, 15A, 100W, <1/3,5µs	16c	Mat	2SC4298, 2SC4424
2SC3528	Si-N	S-L, 500/400V, 20A, 125W, <1/3,5µs	16c	Mat	2SC4425
2SC3529	Si-N	S-L, 500/400V, 5A, 40W, <0,5/1,8µs	17j	Nec	BUT11(A), BUV48(A), 2SC2827, 2SC3497++
2SC353(A)	Si-N	=2SC352: 100V	2a	Son	BSW39, 2N3723
2SC3531	Si-N	S-L, 1000/800V, 3A, 50W, <1/3,5µs	17j	Nec	BUT11A, BUV46A, MJE8502..03, 2SC3457,++
2SC3532	Si-N	S-L, 1000/800V, 4A, 80W, <1/3,5µs	15j	Nec	BUT11A, BUV46A, MJE8502..03, 2SC3491
2SC3533	Si-N	S-L, 1000/800V, 3A, 70W, <1/3,5µs	18j	Nec	BUW11A, BUW131A, 2SC3285, 2SC3534,++
2SC3534	Si-N	S-L, 1000/800V, 4A, 80W, <1/3,5µs	16j	Nec	BUW11A, BUW131A, 2SC3285, 2SC3387,++
2SC3535	Si-N	S-L, 1000/800V, 8A, 100W, <1/3,5µs	16j	Nec	BUW11A, BUW131A, 2SC3387, 2SC3642,++
2SC3536	Si-N	S-L, 1000/800V, 6A, 120W, <1/3,5µs	16j	Nec	BU902..903, BUV47A, BUW12A
2SC3537	Si-N	UHF-L, 50V, 3A, PQ=20W(900MHz)	61v	Nec	—
2SC3536	Si-N	UHF-L, 50V, 6A, PQ=40W(900MHz)	61v	Nec	—
2SC3539	Si-N	UHF-L, 50V, 9A, PQ=60W(900MHz)	61v	Nec	—
2SC354	Si-N	VHF-A/Tr, 40V, 1,5A, 7W, 180MHz	2a	Fui	BFQ43, 2N4427
2SC3540	Si-N	NF/S-L, lo-sat, 100V, 5A, 25W, 120MHz	17c	Tos	2SC3691, 2SC4549, 2SC4596

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2SC3541	Si-N	UHF-L, 35V, 2A, PQ=5,6W(1300MHz)	61v	Nec	—
2SC3542	Si-N	UHF-L, 35V, 6A, PQ=15,8W(1300MHz)	61v	Nec	—
2SC3544	Si-N	UHF, 30V, 0,05A, 0,25W, 2GHz	7f	Nec	BF357, 2SC2498, 2SC2570(A), 2SC3037, ++
2SC3545	Si-N	=2SC3544: SMD	35a	Nec	BFR53, 2SC3014
2SC3546	Si-N	NF/S-L, 160/160V, 12A, 120W, 30MHz	20j	Tos	2SC2526, 2SC2565, 2SC2766(A), 2SC2921, ++
2SC3547(A,B)	Si-N	SMD, UHF-O, TV-Tuner, 20V, 0,03A, 4GHz	35a	Tos	BFQ29, BFR93, BFT75
2SC3548	Si-N	UHF, 20V, 0,03A, 4GHz	25q	Tos	BFQ59..60, BFQ70..71, 2SC2143, ++
2SC3549	Si-N	S-L, 900/800V, 3A, 40W, <1/4,8µs	17j	Fjd	BUT11A, BUV46, 2SC3146, 2SC3490, ++
2SC355	Si-N	VHF-L, 75V, 2,5A, PQ=3W(150MHz)	49a	Fui	BLY35, BLY60, 2N3632
2SC3550	Si-N	S-L, 900/800V, 3A, 60W, <1/4,8µs	18j	Fjd	BUW11A, BUW131A, 2SC3152, 2SC3376, ++
2SC3551	Si-N	S-L, 900/800V, 5A, 60W, <1/4,8µs	18j	Fjd	BUW11A, BUW131A, 2SC3153, 2SC3232, ++
2SC3552	Si-N	S-L, 1100/800V, 12A, 150W, 15MHz	18j	Say	BUV48B,C, BUW13A, 2SC3644
2SC3553	Si-N	Uni, 35V, 0,5A, 0,3W, 120MHz	41c	Hit	BC337..338, BC635, BC637, BC639, ++
2SC3554	Si-N	SMD, S/Vid, 300/300V, 0,2A, 50MHz	39b	Nec	BFN18, 2SC3515, 2SC3380
2SC3555	Si-N	S-L, 900/800V, 0,5A, 20W, <1/5µs	30j	Hit	2SC3405, 2SC3489, 2SD1945, (BUX87, ++)
2SC3556	Si-N	NF/S-L, 60V, 4A, 40W, <0,5/2,5µs	17j	Hit	BD243B, BD537, BD539B, BDV10..12, ++
2SC3557	Si-N	NF/S-L, 60V, 4A, 40W, <0,5/2µs	17j	Hit	BD243B, BD537, BD539B, BDV10..12, ++
2SC3558	Si-N	NF/S-L, 100/60V, 4A, 40W, <0,5/3µs	17j	Tos	BD243C, BD539C, BD953, BDV10..12, ++
2SC3559	Si-N	S-L, 900/800V, 3A, 30W, <1/5µs	17c	Tos	BUT11AF, 2SC3752, 2SC4304, 2SC4234, ++
2SC356	Si-N	SS, 30V, 0,2A, 0,3W, <20/40ns	2a	Nec	BSS11..12, BSW36, 2N2368..69(A), ++
2SC3560	Si-N	S-L, 500/400V, 2A, 20W, -/<1,9µs	17c	Tos	BUX84F..85F, 2SC3309, 2SC3569, 2SC4421
2SC3561	Si-N	S-L, 500/450V, 2A, 20W	17c	Tos	BUX84F..85F, 2SC3309, 2SC3569, 2SC4421
2SC3582	Si-N	S-L, 500/400V, 10A, 40W, -/1,8µs	17c	Tos	2SC3572, 2SC3575, 2SC4162, 2SD1795
2SC3563	Si-N	=2SC3582: 500/450V	17c	Tos	2SC3572, 2SC3575, 2SC4162, 2SD1795
2SC3564	Si-N	NF/S-L, 120V, 1,5A, 200MHz	17c	Nec	2SC3364, (2SC3298(A,B), 2SC4159)
2SC3585	Si-N	Vid/S-L, 300/300V, 0,2A, 15W, 80MHz	17c	Nec	2SC4075, F3646(2SC1505..07, 2SC1755..57, ++)
2SC3566	Si-N	hi-Usb, 150/60V, 5A, 25W, <0,5/3µs	17c	Nec	(2SC3566, 2SC3696, 2SC4153, 2SC4334..35)
2SC3567	Si-N	NF/S-L, 150/100V, 3A, 15W, <0,5/2µs	17c	Nec	BDT31DF, 2SC3695
2SC3568	Si-N	NF/S-L, 150/100V, 10A, 30W, <0,5/2µs	17c	Nec	2SC3698, 2SC4338, (BD743E)
2SC3569	Si-N	S-L, 500/400V, 2A, 15W, <1/3,5µs	17c	Nec	BUX84F..85F, 2SC3560..61, 2SC4421, ++
2SC357..359	Si-N			Nec	—
2SC3570	Si-N	S-L, 500/400V, 5A, 25W, <1/2,7µs	17c	Nec	BUT11(A)F, 2SC3310, 2SC4054, 2SC4371, ++
2SC3571	Si-N	S-L, 500/400V, 7A, 30W, <1/3,5µs	17c	Nec	2SC3690, 2SC4058, 2SC4130, 2SC4161, ++
2SC3572	Si-N	S-L, 500/400V, 10A, 30W, <1/3,2µs	17c	Nec	2SC3310, 2SC3562, 2SC4162, 2SD1795
2SC3573	Si-N	S-L, 500/400V, 5A, 30W, <0,5/1,8µs	17c	Nec	BUT11(A)F, 2SC3310, 2SC4054, 2SC4371, ++
2SC3574	Si-N	S-L, 500/400V, 7A, 30W, <0,5/1,8µs	17c	Nec	2SC3690, 2SC4056, 2SC4130, 2SC4181, ++
2SC3575	Si-N	S-L, 500/400V, 10A, 30W, <0,5/1,8µs	17c	Nec	2SC3310, 2SC3562, 2SC4162, 2SD1795
2SC3576	Si-N	hi-Ueb, hi-beta, lo-saL 30V, 0,3A, B=1500	40c	Say	2SC3068, 2SC3836
2SC3577	Si-N	S-L, 850/650V, 5A, 80W, <1/3µs	16c	Mat	BUW11F, 2SC4300, 2SC4457
2SC3578	Si-N	SMD, S, 40V, 0,1A, <40/70ns	35a	Hit	—
2SC3579	Si-N	S-L, 800/800V, 6A, 50W, <0,5/3,7µs	17j	Shi	BUT11A, BUV46A, 2SC3050, 2SC3047++
2SC3560	Si-N	NF-Tr/E, 25V, 0,7A, 0,9W, 180MHz	7c(9mm)	Mit	BC337..338, 2SC2236, 2SD863, 2SD1331, ++
2SC3581	Si-N	NF-Tr/E, 55V, 0,4A, 0,9W, 150MHz	7c(9mm)	Mit	BC637, 2SC3939, 2SD863, 2SD1937, ++
2SC3582	Si-N	UHF, 20V, 0,065A, 0,6W, 8GHz	7f	Nec	—
2SC3563	Si-N	SMD, UHF, 20V, 0,065A, 9GHz	35a	Nec	—
2SC3584	Si-N	UHF, 20V, 0,065A, 0,2W, 9GHz	25q	Nec	—
2SC3585	Si-N	SMD, UHF, 20V, 0,035A, 10GHz	35a	Nec	—
2SC3566	Si-N	UHF, 20V, 0,035A, 0,25W, 10GHz	25q	Nec	—
2SC3587	Si-N	UHF, 20V, 0,035A, 0,58W, 10GHz	51a	Nec	—
2SC3566	Si-N	S-L, 500/400V, 0,5A, 10W, <1/3,5µs	30j	Nec	2SC3129, 2SC3075, (BUX84..85, 2SC2899)
2SC3569	Si-N	HA, hi-def, lo-sat, 250V, 7A, 40W	17j	Say	(BU406..406, 2SC3173, 2SC3175)
2SC3590	Si-N	HA, hi-del, lo-sat, 330V, 7A, 50W	17j	Say	(BU406..406, 2SC3173, 2SC3175)
2SC3591	Si-N	=2SC3590: 400V	17j	Say	(BU406, BU406, 2SC3175)
2SC3592	Si-N	NF/S-L, 60V, 5A, 10W, <1/3,5µs	30j	Nec	2SC3074, 2SC3518, 2SD1803, (BDV10..12++)
2SC3593	Si-N	S-L, 850V, 25A, 150W, <3/2,5µs	23a	Mat	BUS14(A), BUS98(A)
2SC3594	Si-N	S-L, 1400/650V, 8A, 50W, <500/5,5µs	23a	Hit	BU508(A), BU908, MJ8505, 2SC4284..85
2SC3595	Si-N	Vid-E, hi-def, 30V, 0,5A, 5W, 2GHz	14h	Say	—
2SC3598	Si-N	Vid-E, hi-def, 80V, 0,3A, 8W, 700MHz	14h	Say	2SC3599, 2SC3951
2SC3597	Si-N	Vid-E, hi-def, 60V, 0,5A, 10W, 800MHz	14h	Say	2SC3952
2SC3598	Si-N	Vid-E, hi-del, 120V, 0,2A, 8W, 500MHz	14h	Say	2SC3599, 2SC3953
2SC3599	Si-N	Vid-E, hi-def, 120V, 0,3A, 8W, 500MHz	14h	Say	2SC3954
2SC36	Ge-N	NF/S, 20V, 0,4A, 0,14W, 20MHz	1a	Mat	AC127, ASY73..75
2SC360	Si-N	Uni, 30V, 0,1A, 0,25W, 150MHz	2a	Tos	BC166, BC163, BC238, BC548, 2SD787++
2SC3600	Si-N	Vid-E, hi-del, 200V, 0,1A, 7W, 400MHz	14h	Say	2SC3601, 2SC3955
2SC3601	Si-N	Vid-E, hi-def, 200V, 0,15A, 7W, 400MHz	14h	Say	2SC3958
2SC3602	Si-N	UHF, 25V, 0,02A, 0,2W, 1100MHz	25p	Tos	2SC2464, 2SC2488, 2SC2144, 2SC2360, ++

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2SC3603	Si-N	UHF,20V,0,1A,0,58W,7GHz	51s	Nec	2SC3358
2SC3604	Si-N	UHF,20V,0,065A,0,58W,8GHz	51s	Nec	2SC3358
2SC3605	Si-N	UHF,20V,0,08A,6,5GHz	7f	Tos	2SC2570(A),2SC3037,2SC3512,2SC3355
2SC3606	Si-N	=2SC3605:SMD,7GHz	35a	Tos	2SC3358
2SC3607	Si-N	=2SC3605:SMD	39b	Tos	2SC3357
2SC3608	Si-N	=2SC3605:7GHz	25q	Tos	2SC2876
2SC3609	Si-N	=2SC3605:SMD,7GHz	44u	Tos	—
2SC361	Si-N	HF,25V,40mA,150MHz,β=80	7c	Tos	BF240..241,BF254..255,BF594..595,++
2SC3610	Si-N	Vid-L,hi-res,110V,0,15A,10W,300MHz	17j	Mat	2SC3781
2SC3611	Si-N	=2SC3610:4W	14h	Mat	2SC3598..99
2SC3612	Si-N	Vid-E,hi-res,180V,0,3A,20W,400MHz	17j	Tos	—
2SC3613	Si-N	Vid-Tr,hi-res,20V,0,5A,5W,3500MHz	14b	Tos	—
2SC3614	Si-N	SMD,VHF/UHF,20V,0,1A	39b	Hit	—
2SC3615	Si-N	hi-Ueb,hi-beta,50V,0,3A,B>800,220MHz	7c	Nec	2SC3636,2SD1915
2SC3616	Si-N	hi-Ueb,hi-beta,25V,0,7A,B>800,250MHz	7c	Nec	2SC3070,2SC4204,2SD1582
2SC3617	Si-N	=2SC3615:SMD	39b	Nec	—
2SC3618	Si-N	=2SC3616:SMD	39b	Tos	2SC3650
2SC3619	Si-N	S,Vid-L,300/300V,0,1A,>50MHz	14b	Tos	2SC3789..90,(BF758..759,MPS-U10,++)
2SC362	Si-N	=2SC361:β=140	7c	Tos	TBF240..241,BF254..255,BF594..595,++
2SC3620	Si-N	Vid-L,300/300V,0,1A,>50MHz	14b	Tos	2SC3789..90,(BF758..759,MPS-U10,++)
2SC3621	Si-N	CTV-HA,NF-E,150V,1,5A,10W,100MHz	14b	Tos	2SC3902,(2SC3117,2SD669,2SD781)
2SC3622(A)	Si-N	hi-beta,hi-Ueb,80V,0,15A,B=1800	7c	Nec	2SC3069,2SC3836
2SC3623(A)	Si-N	=2SC3622:	40c	Nec	2SC3069,2SC3836
2SC3624(A)	Si-N	=2SC3622:SMD	35a	Nec	2SC3689
2SC3625	Si-N	S-L,500/400V,8A,80W,<1/3,5µs	17j	Tos	BUT54,BUT58(A),2SC3562,2SC4107,++
2SC3626	Si-N	=2SC3625:40W	17c	Tos	2SC3574..75,2SC3890,2SC4130,2SC4181++
2SC3627	Si-N	S-Reg,250/200V,10A,40W,<1/3,5µs	17c	Tos	2SC3572,2SC3575,2SC4162,2SD1795,++
2SC3626	Si-N	VHF-L,35V,2A,PQ=8,5W(175MHz)	58s	Mit	—
2SC3629	Si-N	UHF-L,20V,1A,PQ=1,5W(520MHz)	58s	Mit	—
2SC363	Si-N	=2SC361:β=250	7c	Tos	BF240..241,BF254..255,BF594..595,++
2SC3630	Si-N	UHF-L,35V,1A,PQ=3,3W(520MHz)	58s		—
2SC3631(Z)	Si-N	S-L,500/400V,2A,10W,50MHz	30j	Nec	2SC3233,(BUV93..94)
2SC3632(Z)	Si-N	S-L,600/600V,1A,10W,30MHz	30j	Nec	2SC3363
2SC3633	Si-N+Di	=2SC3636:integr.Damper-Diode	18j	Say	2SC3639
2SC3634	Si-N+Di	=2SC3637:integr.Damper-Diode	18j	Say	2SC3640
2SC3635	Si-N+Di	=2SC3638:integr.Damper-Diode	18j	Say	2SC3641
2SC3636	Si-N	HA,hi-def,900/500V,7A,80W	18j	Say	2SC3643
2SC3637	Si-N	HA,hi-def,900/500V,10A,90W	18j		2SC3644
2SC3636	Si-N	HA,hi-def,900/500V,15A,100W	18j	Say	—
2SC3639	Si-N+Di	=2SC3642:integr.Damper-Diode	18j	Say	—
2SC364	Si-N	=2SC361:β=400	7c	Tos	BF240..241,BF254..255,BF594..595,++
2SC3640	Si-N+Di	=2SC3643:integr.Damper-Diode	18j	Say	—
2SC3641	Si-N+Di	=2SC3644:integr.Damper-Diode	18j	Say	—
2SC3642	Si-N	HA,hi-def,1200/800V,6A,100W	18j	Say	2SC3686..87
2SC3643	Si-N	HA,hi-def,1200/800V,8A,140W	18j	Say	2SC3466
2SC3644	Si-N	HA,hi-def,1200/800V,12A,150W	18j	Say	—
2SC3645	Si-N	SMD,Uni,180/180V,0,14A,150MHz	39b	Say	BFN16,BFN18
2SC3646	Si-N	SMD,Uni,120V,1A,120MHz	39b	Say	2SC3647,2SC4132,2SC4373,2SD141819
2SC3647	Si-N	SMD,Uni,120V,2A,120MHz	39b	Say	2SC4132
2SC3648	Si-N	SMD,Uni,180V,0,7A,120MHz	39b	Say	2SC3649,2SD1420..1421
2SC3649	Si-N	SMD,Uni,180V,1,5A,120MHz	39b	Say	2SD1420..1421
2SC3650	Si-N	SMD,hi-Ueb,hi-beta,30V,1,2A,B=1500	39b	Say	(2SD1950)
2SC3651	Si-N	SMD,hi-Ueb,hi-beta,120V,0,2A,B>500	39b	Say	—
2SC3652	Si-N	HF-L,30V,0,3A,5W,1200MHz	14h	Hit	—
2SC3653	Si-N+R	=2SC3399:0,4W	7c	Say	→2SC3399
2SC3654	Si-N+R	=2SC3400:0,4W	7c	Say	→2SC3400
2SC3655	Si-N+R	=2SC3401:0,4W	7c	Say	→2SC3401
2SC3658	Si-N+R	=2SC3402:0,4W	7c	Say	→2SC3402
2SC3657	Si-N	S-L,900/800V,4A,80W,<1/3,5µs	18j	Tos	BUW11A,2SC3153,2SC3232,2SC3535,++
2SC3658	Si-N+Di	S-L,TV-HA,1500/800V,5A,50W	23a	Hit	BU208D,BU508D,2SC4291,2SD1171..75++
2SC3659	Si-N+Di	S-L,TV-HA,1700/800V,5A,50W	23a	Hit	(BU209,2SC3026,2SD764..785)
2SC366(G,GTM)	Si-N	Uni,50..80V,0,4A,0,3W,120MHz	7c	Tos	BC337(A),BC637,BC639,2SD1226,++
2SC3660(A)	Si-N	UHF-L,55V,24A,PQ=105W(620MHz)		Nec	—
2SC3661	Si-N	SMD,hi-Ueb,hi-beta,30V,0,3A,B=1500	35a	Say	2SD1938
2SC3662	Si-N	SMD,UHF,25V,0,02A,1100MHz	44o	Tos	—
2SC3663	Si-N	SMD,UHF,15V,5mA,4GHz	35a	Nec	BFQ29,BFQ81,BFR93,2SC3099

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2SC3664	Si-N-Darl+Di	S-L, 800/400V, 20A, 150W, B>80	18j	Say	—
2SC3665	Si-N	Uni, 120V, 0,8A, 1W, 120MHz	9c	Tos	2SC2235, 2SC3665, 2SD667, 2SD1616A, ++
2SC3666	Si-N	Uni, 30V, 1A, 1W, 150MHz	9c	Tos	BC337..336, BC635, BC637, BC639, ++
2SC3667	Si-N	Uni, 30V, 1,5A, 1W, 120MHz	9c	Tos	MPS650..651, 2SC2236, 2SD1051, 2SD1331++
2SC3668	Si-N	Uni, 50V, 2A, 1W, 100MHz	9c	Tos	MPS650..651, 2SD1014, 2SD1146, 2SD1207++
2SC3689	Si-N	Uni, 80V, 2A, 1W, 100MHz	9c	Tos	MPS651, 2SC3328, 2SC3669, 2SC4145
2SC367(G,GTM)	Si-N	Uni, 40V, 0,4A, 0,3W, 120MHz	7c	Tos	BC337, BC635, BC637, 2SD1225..26, ++
2SC3670	Si-N	Strobo flash, lo-sat, 30V, 2A, 1W, 150MHz	9c	Tos	2SC4484, 2SC4486, 2SD1207, 2SD1246..47
2SC3671	Si-N	Strobo flash, 50V, 5A, 1W, 100MHz	9c	Tos	2SC4482, 2SD1145, 2SD1961..62, 2SD2179
2SC3672	Si-N	Vid, 300/300V, 0,1A, 1W, 80MHz	9c	Tos	BF299, BF393, BF420A, 2SC3468, ++
2SC3673	Si-N	hi-beta, 40V, 2A, 1W, 220MHz, B=1000	9c	Tos	2SC3225
2SC3674	Si-N	UHF, 15V, 0,065A, 0,4W, 8GHz	51s	Mat	BFQ66, 2SC3603
2SC3675	Si-N	Dynamic Focus, 1500/900V, 0,1A, 10W	17j	Say	—
2SC3676	Si-N	Dynamic Focus, 1500/900V, 0,3A, 20W	17j	Say	—
2SC3677	Si-N	NF/S-L, 80V, 3A, 25W, 170MHz, B=2000	17c	Tos	2SD1273, 2SD1972, 2SD2177
2SC3678	Si-N	S-L, 900/800V, 3A, 80W, 6MHz, <1/6µs	18j	Sak	BUW11A, 2SC3152, 2SC3285, 2SC3550, ++
2SC3679	Si-N	S-L, 900/800V, 5A, 100W, 6MHz, <1/6µs	18j	Sak	BUW11A, 2SC3153, 2SC3387, 2SC3466, ++
2SC368	Si-N	Uni, ra, 25V, 0,1A, 0,25W, 150MHz	2a	Tos	BC169, BC184, BC239, BC549, 2SC2675+
2SC3680	Si-N	S-L, 900/800V, 7A, 120W, 6MHz, <1/6µs	18j	Sak	BUV47A, BUW12A, 2SC3466, 2SC3636, ++
2SC3661	Si-N+Di	=2SC3665: integr. Damper-Diode	18j	Say	2SC3482, 2SC4292, (BU508D, BU706D)
2SC3682	Si-N+Di	=2SC3666: integr. Damper-Diode	18j	Say	(BU508D)
2SC3683	Si-N+Di	=2SC3667: integr. Damper-Diode	18j	Say	BU2520D
2SC3684	Si-N+Di	=2SC3668: integr. Damper-Diode	18j	Say	BU2520D
2SC3665	Si-N	TV-HA, hi-def, 1500/800V, 6A, 120W	16c	Say	2SC3486, (BU508A, BU706, BU908)
2SC3686	Si-N	TV-HA, hi-def, 1500/800V, 7A, 120W	16c	Say	2SC3667, (BU508A, BU908)
2SC3667	Si-N	TV-HA, hi-def, 1500/800V, 8A, 150W	16c	Say	BU2520A
2SC3686	Si-N	TV-HA, hi-def, 1500/800V, 10A, 150W	16c	Say	BU2520A
2SC3669	Si-N	SMD, hi-Ueb, hi-beta, 60V, 0,1A, B=1500	35a	Say	2SC3651, (2SC4413)
2SC369(G)	Si-N	=2SC368: 0,2W	7c	Tos	BC169, BC184, BC239, BC549, 2SC2675+
2SC3690	Si-N	S-L, lo-sat, 100V, 3A, 15W, <300/1800ns	17c	Nec	2SC3695
2SC3691	Si-N	S-L, 100V, 5A, 25W, <300/1800ns	17c	Nec	2SC3696, 2SC4549
2SC3692	Si-N	S-L, 100V, 7A, 30W, <300/1800ns	17c	Nec	2SC3697, 2SC4550
2SC3693	Si-N	S-L 100V, 10A, 30W, <300/1800ns	17c	Nec	2SC3696, 2SC4551
2SC3694	Si-N	S-L 100V, 15A, 30W, <300/1800ns	17c	Nec	2SC3699, 2SC4552
2SC3695	Si-N	S-L 150V, 3A, 15W, <300/1800ns	17c	Nec	—
2SC3696	Si-N	S-L, 150V, 5A, 20W, <300/1800ns	17c	Nec	—
2SC3697	Si-N	S-L 150V, 7A, 25W, <300/1800ns	17c	Nec	—
2SC3698	Si-N	S-L 150V, 10A, 30W, <300/1800ns	17c	Nec	—
2SC3699	Si-N	S-L, 150V, 15A, 30W, <300/1800ns	17c	Nec	—
2SC37	Si-N	HF-Tr, 40V, 0,1A, 0,2W, 200MHz	2a	Nec	BFW16..17, BFX55
2SC370(G,T)	Si-N	Uni, 35..40V, 0,1A, 0,2W, 200MHz, B>20	7c	Tos	BC167, BC183, BC237, BC547, 2SD767++
2SC3700	Si-N	UHF-L, 55V, 6A, PQ=30W(880MHz)	61s	Fui	—
2SC3701	Si-N	UHF-L, 55V, 12A, PQ=50W(860MHz)	61s	Fui	—
2SC3702	Si-N	UHF-L, 55V, 20A, PQ=80W(860MHz)	61s	Fui	—
2SC3703	Si-N	S-L, 230/230V, 30A, 300W, <0,7/2µs	6Sa	Shi	2SC2940, 2SC3224
2SC3704	Si-N	SMD, UHF, ra, 15V, 0,08A, 6GHz	35a	Mat	2SC3356, 2SC3445, 2SC3606
2SC3705	Si-N-Darl+Di	NF/S-L, 50V, 1,2A, 10W, 180MHz, B=4000	14b(H)	Say	—
2SC3706	Si-N	S-L, 230/230V, 50A, 200W, <1,2/2,5µs	68a	Sak	2SC1437, 2SC2942
2SC3707	Si-N	SMD, UHF, 10V, 0,01A, 4GHz	35a	Mat	BFR92, 2SC3099, 2SC3110
2SC3708	Si-N	Uni, 100V, 0,5A, 0,6W, 120MHz	7c	Say	BC639, 2SC2235, 2SD667, 2SD1768, ++
2SC3709	Si-N	lo-sat, 60V, 12A, 30W, 90MHz, 200/1200ns	17c	Tos	2SC4065
2SC371(G,T)	Si-N	=2SC370: 30V, B>40	7c	Tos	BC187, BC183, BC237, BC547, 2SD767++
2SC3710	Si-N	=2SC3709: 80V, 80MHz	17c	Tos	—
2SC3711	Si-N	Uni, 80V, 0,1A, 0,2W, 200MHz	41c	Tos	BC174, BC182, BC190, BC546, ++
2SC3712	Si-N	UHF-L, 35V, 16A, PQ>5080W(860MHz)	81v	Nec	—
2SC3713	Si-N	SMD, Uni, 60V, 0,1A, 200MHz	35a	Tos	BC846, BCV71..72, 2SC3323, ++
2SC3714	Si-N	S-L, 500/400V, 20A, 200W, <500/2300ns	77j	Shi	2SC3498..99
2SC3715	Si-N+Di+Rbe=50	TV-HA, 1500/600V, 4A, 50W, <2/5,5µs	16c	Tos	BU508DF, 2SC4293..94, 2SD1555..56, ++
2SC3716	Si-N+Di+Rbe=50	TV-HA, 1500/800V, 5A, 50W, <2/5,5µs	16c	Tos	BU508AF, 2SD1545..46, 2SD1655..56, ++
2SC3717	Si-N	FMA/HF, 30V, 0,05A, 0,2W, 750MHz	41c	Tos	BF225, BF255, BF310, BF314, BF496++
2SC3718	Si-N	=2SC3717 SMD	35a	Tos	BF599, BF799, 2SC3015, 2SC3374
2SC3719	Si-N	S-L, TV-HA, 1200/800V, 5A, 150W	23a	Mat	—
2SC372(G,GTM)	Si-N	Uni, 35V, 0,1A, 0,2W, 200MHz, B>70	7c	Tos	BC167, BC183, BC237, BC547, 2SD767++
2SC3720	Si-N	S-L, TV-HA, 1200/800V, 10A, 200W	23a	Mat	—
2SC3721	Si-N	UHF, 15V, 0,05A, 0,2W, 7GHz	25q	Hit	BFG65, BFQ68
2SC3722	Si-N	SMD, NF, ra, 120V, 0,05A, 140MHz	≈35d	Rhm	—

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2SC3722K	Si-N	=2SC3722:	35a		2SC3324
2SC3723	Si-N	S-L, 450/400V, 5A, 40W, <1/3µs	17j	Fjd	BUT11(A), MJE53T, 2SC2542, 2SC3056, ++
2SC3724	Si-N	S-L, 450/400V, 10A, 80W, <1/3µs	18j	Fjd	BUV47(A), BUW12(A), 2SC2625, 2SC3042++
2SC3725	Si-N	S-L, 450/400V, 15A, 80W, <1/3µs	18j	Fjd	BUV48(A), BUW13(A), 2SC3520, 2SC3451++
2SC3726	Si-N	hi-beta, 50V, 2A, 0,9W, 150MHz, B=1200	7c(9mm)	Mit	2SD1779
2SC3727	Si-N	=2SC3726: SMD	39b	Mit	—
2SC3728	Si-N	SMD, int. Z-Diode(C→E), 20V, 2A, 80MHz	39b	Mit	—
2SC3729	Si-N	S-L, TV-HA, 1500/800V, 5A, 50W	18j	Hit	BU508A, BU908, 2SC3485..86, 2SC3685, ++
2SC373(G,GTM)	Si-N	=2SC372: B>200	7c	Tos	BC167, BC183, BC237, BC547, 2SD767++
2SC3730	Si-N	SMD, UHF, ra, 15V, 0,05A, 7,5GHz	35a	Hit	BFQ67, 2SC3445
2SC3731	Si-N	S, 80V, 0,2A, 0,25W, <70/250ns	40c	Nec	—
2SC3732	Si-N	HF/S, 40V, 0,2A, 0,25W, <12/18ns	40c	Nec	—
2SC3733	Si-N	HF/S, 80V, 1A, 1W, <40/110ns	9b	Nec	—
2SC3734	Si-N	=2SC3731: SMD	35a	Nec	—
2SC3735	Si-N	=2SC3732: SMD	35a	Nec	—
2SC3736	Si-N	=2SC3733: SMD	39b	Nec	—
2SC3737	Si-N	S-L, 1200/800V, 5A, 100W, <1/3,8µs	16c	Mat	2SC4584
2SC3738	Si-N	S-L, 1200/800V, 10A, 175W, <1/3,8µs	77j	Mat	2SC4096
2SC3739	Si-N	SMD, HF/S, 80V, 0,5A, <35/275ns	36a	Nec	BSR13..14, BSS79, BSS81
2SC374	Si-N	Uni, 35V, 0,1A, 0,2W, 150MHz	7c	Tos	BC187, BC183, BC237, BC547, 2SD767++
2SC3740	Si-N	S, 30V, 1A, 0,75W, <1/3µs	7c	Nec	—
2SC3741	Si-N	=2SC3740:	40c	Nec	—
2SC3742	Si-N	=2SC3740: SMD	35a	Nec	—
2SC3743	Si-N	S-L, 900/800V, 3A, 40W, <1/5µs	17c	Mat	BUT11AF, 2SC3559, 2SC3752, 2SC4304, ++
2SC3744	Si-N	SMD, Uni, 180/180V, 0,1A, 100MHz	35a	Hit	2SD1305
2SC3745	Si-N	SMD, UHF, 20V, 0,03A, 8,5GHz	44u	Tos	—
2SC3746	Si-N	S-L, lo-sat, 80V, 5A, 20W, 100/800ns	17c	Say	(2SC3253, 2SC3258)
2SC3747	Si-N	S-L, lo-sat, 80V, 7A, 25W, 100/600ns	17c	Say	(2SC3254)
2SC3748	Si-N	S-L, lo-sat, 80V, 10A, 30W, 100/600ns	17c	Say	(2SC3255)
2SC3749	Si-N	S-L, 800/500V, 3A, 25W, <500/3300ns	17c	Say	2SC3559, 2SC4304, 2SD1571
2SC375	Si-N	VHF, 20V, 50mA, 600MHz	7c	Tos	BF196..199, BF224..225, BF505, ++
2SC3750	Si-N	S-L, 800/500V, 5A, 30W, <500/3300ns	17c	Say	BUT11(A)F, 2SC3353
2SC3751	Si-N	S-L, 1100/800V, 1,5A, 25W, <500/3300ns	17c	Say	2SC4231
2SC3752	Si-N	S-L, 1100/800V, 3A, 30W, <500/3300ns	17c	Say	2SC4234
2SC3753	Si-N+Di	S-L, TV-HA, 1500/800V, 5A, 60W	18c	Say	BU505DF, 2SC4293..94, 2SD1651..52, ++
2SC3754	Si-N+Di	S-L, TV-HA, 1500/800V, 6A, 60W	18c	Say	BU508DF, 2SC4294, 2SC4142, 2SD1652, ++
2SC3755	Si-N	S-L, TV-HA, 1500/800V, 5A, 60W	18c	Say	BU508AF, 2SC3694, 2SC4142..43, 2SD1545+
2SC3756	Si-N	S-L, TV-HA, 1500/800V, 6A, 60W	16c	Say	BU506AF, 2SC3694, 2SC4143, 2SD1546, ++
2SC3757	Si-N	SMD, S, 40V, 0,1A, 17/17ns	35a	Mat	2SC3578
2SC3758	Si-N	S-L, 500/400V, 10A, 70W, <300/1800ns	18c	Nec	2SC4423
2SC3759	Si-N	S-L, 500/400V, 15A, 75W, <500/1800ns	16c	Nec	2SC4424
2SC376	Si-N	Uni, 70V, 0,1A, 0,2W, 150MHz	7c	Tos	BC174, BC182, BC190, BC548, 2SC1890+
2SC3760	Si-N	S-L, 500/400V, 10A, 65W, <1000/3200ns	16c	Nec	2SC4423
2SC3761	Si-N	S-L, 500/400V, 15A, 75W, <1000/3200ns	16c	Nec	2SC4424
2SC3762	Si-N	S-L, 150/100V, 15A, 65W, <1000/1800ns	16c	Nec	—
2SC3763	Si-N	S-L, 1000/800V, 3A, 60W, <1000/3500ns	16c	Nec	2SC4426
2SC3764	Si-N	S-L, 1000/800V, 4A, 65W, <1000/3500ns	18c	Nec	2SC4427
2SC3765	Si-N	S-L, 1000/800V, 6A, 70W, <1000/3500ns	18c	Nec	2SC4428
2SC3766	Si-N	S-L, 1000/800V, 8A, 75W, <1000/3500ns	16c	Nec	2SC4429
2SC3769	Si-N+Di+Rbe=50	TV-HA, 1500/600V, 8A, 50W, <500/5500ns	23a	Hit	BU508(A), BU908, 2SC3027..3028
2SC377	Si-N	HF, 35V, 0,03A, 0,2W, 150MHz	7c	Tos	BF240..241, BF254..255, BF594..595, ++
2SC3770	Si-N	SMD, VHF/UHF, 30V, 0,03A, 1200MHz	35a	Say	BF517, BFS17, 2SC3005, 2SC3016
2SC3771	Si-N	SMD, VHF/UHF, 30V, 0,03A, 2200MHz	35a	Say	BFR35, BFR53, BFT25, 2SC3014
2SC3772	Si-N	SMD, UHF, 25V, 0,07A, 3000MHz	35a	Say	2SC3161, 2SC3774..75
2SC3773	Si-N	SMD, UHF, 25V, 0,05A, 3500MHz	35a	Say	BFT75, 2SC3014
2SC3774	Si-N	SMD, UHF, 20V, 0,07A, 5000MHz	35a	Say	2SC3161
2SC3775	Si-N	SMD, UHF, 20V, 0,1A, 5000MHz	35a	Say	—
2SC3776	Si-N	UHF, 25V, 0,07A, 3000MHz	7f	Say	2SC2570(A), 2SC3037, 2SC3337
2SC3777	Si-N	UHF, 25V, 0,05A, 3500MHz	7f	Say	2SC2496, 2SC2570(A), 2SC3037, 2SC3337
2SC3778	Si-N	UHF, 20V, 0,07A, 5000MHz	7f	Say	2SC2570(A), 2SC3037, 2SC3337
2SC3779	Si-N	UHF, 20V, 0,1A, 5000MHz	7f	Say	2SC3355
2SC378	Si-N	HF, 35V, 0,03A, 0,2W, 150MHz	7c	Tos	BF240..241, BF254..255, BF594..595, ++
2SC3780	Si-N	Vid-E, hi-def, 80V, 0,8A, 15W, 800MHz	17j	Say	—
2SC3781	Si-N	Vid-E, hi-def, 120V, 0,4A, 15W, 500MHz	17j	Say	—
2SC3782	Si-N	Vid-E, hi-def, 200V, 0,2A, 15W, 400MHz	17j	Say	—
2SC3783	Si-N	S-L, 900/800V, 5A, 100W, <1/4,5µs	18j	Tos	BUW11A, BUW131A, BUV82, 2SC3796A, ++

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2SC3784	Si-N-Darl+Di	+Z-Di, 50V, 1,2A, 20W, 180MHz, B=4000	14b(H)	Say	—
2SC3785	Si-N-Darl+Di	+Z-Di, 50V, 2A, 20W, 180MHz, B=4000	14b(H)	Say	—
2SC3786	Si-N	+Z-Di, 50V, 3A, 20W, 180MHz	14b	Say	—
2SC3787	Si-N	NF-Tr, 180V, 0,14A, 10W, 150MHz	14b	Say	2SC3788, (BF415, BF417, 2SC3502. 03,+)
2SC3786	Si-N	Vid-E, hi-def, 200V, 0,1A, 5W, 150MHz	14b	Say	2SC3956, (2SC3502. 03)
2SC3789	Si-N	Vid-E, hi-def, 300V, 0,1A, 7W, 70MHz	14b	Say	(2SC3417, 2SC3503)
2SC379	Si-N	HF, 30V, 0,1A, 0,2W, 300MHz	7c	Tos	BF198..199, BF224 225, BF505,++
2SC3790	Si-N	Vid-E, hi-def, 300V, 0,1A, 7W, 150MHz	14b	Say	(2SC3417, 2SC3503)
2SC3791	Si-N	UHF, ra, 15V, 0,08A, 0,25W, 6GHz	25q	Mat	2SC3358, 2SC3603
2SC3792	Si-N	50V, Ueb=25V, 0,5A, 0,5W, 250MHz, B>300	7c	Say	(2SD1582)
2SC3793	Si-N	SMD, UHF-O, 20V, 0,05A, 2900MHz	35a	Hit	BFT75, 2SC3014, 2SC3773
2SC3794	Si-N	S-L, 800/500V, 1,5A, 25W, <1/4µs	17c	Mat	BUX84F. 85F, 2SC3352
2SC3794A	Si-N	=2SC3794: 900/500V, <1,2/4,2µs	17c		BUX85F, 2SC3751, 2SC4231
2SC3795	Si-N	S-L, 800/500V, 5A, 40W, <1/4µs	17c	Mat	BUT11(A)F, 2SC3353, 2SC3750
2SC3795A	Si-N	=2SC3795 900/500V, <1,2/4,2µs	17c		BUT11AF, BUT18AF, BUT21CF
2SC3796	Si-N	S-L, 800/500V, 5A, 70W, <1/4µs	18j	Mat	BUW11(A), BUW131(A), 2SC3089, 2SC3636+
2SC3796A	Si-N	=2SC3796: 900/500V, <1,2/4,2µs	18j		BUW11A, BUW131A, 2SC3636, 2SC3642
2SC3797	Si-N	S-L, 800/500V, 7A, 100W, <1/4µs	18j	Mat	BUV47(A), BUW12(A), 2SC3449, 2SC3636,+
2SC3797A	Si-N	=2SC3797: 900/500V, <1,2/4,2µs	18j		BUV47A, BUW12A, 2SC3466, 2SC3636
2SC3798	Si-N	S-L, 800/500V, 5A, 70W, <1/4µs	16c	Mat	BUW11(A)F, 2SC4300, 2SC4457
2SC3798A	Si-N	=2SC3798: 900/500V, <1,2/4,2µs	16c		BUW11AF, 2SC4300. 2SC4427
2SC3799	Si-N	S-L, 800/500V, 7A, 100W, <1/4µs	16c	Mat	BUV47(A)FI, BUW12(A)F, 2SC4301
2SC3799A	Si-N	=2SC3799. 900/500V, <1,2/4,2µs	16c		BUV47AFI, BUW12AF, 2SC4301. 2SC4429
2SC36	Si-N	=2SC37 0,5W	2a	Nec	BFW16. 17, BFX55
2SC360(TM,ATM)	Si-N	FM-ZF, 35V, 30mA, 250MHz	7c	Tos	BF240 241, BF254 255, BF594. 595,++
2SC3600	Si-N	Uni, ra. 150V, 0,05A, 0,8W, 140MHz	7c(9mm)	Rhm	2SC2632, 2SC3245A, 2SC3248
2SC3601	Si-N	UHF, 30V, 0,03A, 0,25W, 1100MHz	7f	Rhm	BF377 378, BF763, 2SC2570(A),++
2SC3802K	Si-N	=2SC3601 SMD	35a	Rhm	BF517, BFS17, 2SC3018, 2SC3181
2SC3603	Si-N	SMD, Uni, 80V, 0,2A, 200MHz	39b	Tos	—
2SC3804	Si-N	UHF-L, 35V, 12A, PQ=45W(860MHz)	81t	Mit	—
2SC3605	Si-N	HF/Vid-L, 300/300V, 0,1A, 10W, 70MHz	30j	Tos	2SC2870, 2SC3408, 2SC2924, 2SC4019
2SC3906	Si-N	UHF, ra, 15V, 0,05A, 0,15W, 4500MHz	5g	Hit	BFQ63
2SC3807	Si-N	hi-beta, lo-sat, hi-Ueb, 30V, 2A, B>800	≈14h	Say	—
2SC3808	Si-N	hi-beta, lo-sat, hi-Ueb, 80V, 2A, B>800	≈14h	Sey	—
2SC3809	Si-N	DueL, UHF, 20V, 0,1A, 0,3W, 7GHz		Nec	—
2SC361	Si-N	FM-ZF, 40V, 20mA, >250MHz	7c	Tos	BF240. 241, BF254 255, BF594. 595,++
2SC8610	Si-N	DueL. UHF, 20V, 0,085A, 0,3W, 8GHz		Nec	—
2SC3811	Si-N	S, 40V, 0,1A, 0,4W, 450MHz, 17/17ns	7e	Mat	BSV91..92, BSX92 .93, 2N2380(A),++
2SC3812	Si-N	DueL, VHF-L, 55V, 48A, PQ=200W(230MHz)		Nec	—
2SC3813	Si-N	S-L, 300/100V, 7A, 150W, 10MHz	18j	Tos	TIP55A 58A, 2SC2305, 2SC2656,++
2SC3814	Si-N	UHF-L, 20V, 0,5A, PQ=1W(940MHz)		Nec	—
2SC3815	Si-N	UHF-L, 20V, 1,5A, PQ=3,2W(940MHz)		Nec	—
2SC3816	Si-N	UHF-L, 20V, 3A, PQ=8,3W(940MHz)		Nec	—
2SC3817	Si-N	UHF-L, 35V, 0,5A, PQ=1W(1550MHz)	81r	Nec	—
2SC3818	Si-N	UHF-L, 35V, 2A, PQ=4W(1550MHz)	61r	Nec	—
2SC3819	Si-N	UHF-L, 35V, 4A, PQ=10W(1550MHz)	81r	Nec	—
2SC362(TM)	Si-N	TV-ZF, VHF-re, 800MHz	7c	Tos	BF198, BF225, BF310, BF367, BF505++
2SC3620	Si-N	hi-Ueb, hi-beta, 80V, 0,1A, B=1500	40c	Sey	2SC3069, 2SC3071, 2SC3636, (2SC3622)
2SC3821	Si-N	S-L, 450/400V, 5A, 40W, <1/3,5µs	17c	F|d	2SC3570, 2SC3573, 2SC4054
2SC3622	Si-N	S-L, 450/400V, 5A, 30W, <1/3,5µs	17c	F|d	2SC3570. 2SC3573, 2SC4054
2SC3823	Si-N	S-L, 120V, 5A, 40W, <1/3,5µs	17j	Hit	BDV10. 12, MJE15028, 2SD772
2SC3624(A)	Si-N	=2SC3498(A): 15W	≈30j	Mat	—
2SC3625	Si-N	=2SC3403: 15W	≈30j	Mat	2SC3233, 2SC3631
2SC3626	Si-N	S-L, 200/100V, 5A, 30W, <500/2800ns	17j	Nec	2SC2767, 2SD772A,B, 2SC1274A,B
2SC3827	Si-N	SMD, UHF-O, 30V, 0,02A, 1300MHz	35a	Nec	BF517, BFS17, 2SC3005, 2SC3018
2SC3828	Si-N	SMD, TV-UHF-Tuner, 25V, 0,02A, 1100MHz	44o	Tos	—
2SC3629	Si-N	SMD, UHF, 15V, 0,08A, 6000MHz	35a	Mat	2SC3445, 2SC3606, 2SC3704
2SC363	Si-N	TV-ZF-E, 75V, 0,05A, 0,3W, >300MHz	7c	Tos	(BF199, BF224, BF311, BF373,++)
2SC3830	Si-N	S-Reg, 600/500V, 6A, 50W, <1/5µs	17j	Sak	BUT11(A), BUV46(A), 2SC3087, 2SC4055++
2SC3631	Si-N	S-Reg, 600/500V, 10A, 100W, <1/5µs	18j	Sak	BUV47(A), BUW12(A), 2SC3450, ++
2SC3832	Si-N	S-Reg, 500/400V, 7A, 50W, <1/3,5µs	17j	Sak	BUT54. BUT56(A), 2SC3039, 2SC3170, ++
2SC3633	Si-N	S-Reg, 500/400V, 12A, 100W, <1/3,5µs	18j	Sak	BUV48(A C), BUW13(A), 2SC3520, ++
2SC3634	Si-N	S-Reg, 200/120V, 7A, 50W, <500/3500ns	17j	Sek	BU406 409, TIP150 .152, 2SC2335,++
2SC3635	Si-N	S-Reg, 200/120V, 7A, 70W, <500/3500ns	18j	Sak	TIP55A 58A, 2SC2305, 2SC2656,++
2SC3636	Si-N	hi-Ueb, hi-beta, lo-sat, 60V, 0,3A, B>800	41c	Hit	(2SD1582)
2SC3637K	Si-N	SMD, VHF/UHF, 30V, 0,05A, 1500MHz	35a	Rhm	BF517, BF799, 2SC3015. 16, 2SC3161, ++

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2SC3838K	Si-N	SMD, UHF, 20V, 0,05A, 3200MHz	35a	Rhm	BF775, 2SC3014, 2SC3098, 2SC3773, ++
2SC3839K	Si-N	SMD, VHF/UHF, 30V, 0,05A, 2000MHz	35a	Rhm	BFR53, 2SC3014, 2SC3098, 2SC3773, ++
2SC383TM, ATM	Si-N	=2SC383: 50(ATM=30V)	7c		BF199, BF224, BF311, BF373, ++
2SC384	Si-N	VHF, 20V, 0,05A, 0,2W, 500MHz	7c	Tos	BF198..199, BF224..225, BF505, ++
2SC3840	Si-N	S-L, 600/600V, 1A, 15W, 30MHz	14h	Nec	(BUV63, 2SC3632)
2SC3841	Si-N	SMD, UHF-O, 25V, 0,03A, 4GHz	35a	Nec	BFQ29, BFQ61, BFR93, BFT75
2SC3842	Si-N	S-L, TV-HA, 600/400V, 10A, 70W, 32MHz	18c	Fui	(BUV47(A), BUW12(A), 2SC3831, ++)
2SC3843	Si-N	S-L, TV-HA, 600/450V, 10A, 75W 28MHz	18c	Fui	(BUV47(A), BUW12(A), 2SC3831, ++)
2SC3844	Si-N	S-L, TV-HA, 600/450V, 15A, 75W 30MHz	18c	Fui	(BUV48(A), BUW13(A), 2SC3451, ++)
2SC3845	Si-N	S-L, TV-HA, 1200/800V, 3A, 75W 15MHz	18c	Fui	2SC4426, (2SC3387, 2SC3642)
2SC3846	Si-N	S-L, TV-HA, 1200/800V, 6A, 80W, 15MHz	18c	Fui	2SC4426, (BUV89, 2SC3466, 2SC3643)
2SC3847	Si-N	S-L, TV-HA, 1200/800V, 10A, 85W 15MHz	18c	Fui	BU2520AF, 2SC4199, (BUV70..71)
2SC3848	Si-N				—
2SC3849	Si-N	Dual, UHF-E, 20V, 0,08A, 7GHz		Rhm	—
2SC385(A)	Si-N	VHF, 20V, 0,02A, 0,2W, 600MHz	7c	Tos	BF198..199, BF224..225, BF505, ++
2SC3850	Si-N	S-L, 500/400V, 20A, 125W, <1/3,5µs	18j	Mat	2SC4110
2SC3851	Si-N	NF/S-L, lo-sat, 80V, 4A, 25W, 15MHz	17c	Sak	2SD1411
2SC3851A	Si-N	=2SC3851: 100V	17c		2SD1411
2SC3852	Si-N	hi-beta, lo-sat, 80V, 3A, 25W, 15MHz, B>500	17c	Sak	2SD2092, (2SD1944, 2SD1273A, 2SD2156A)
2SC3852A	Si-N	=2SC3852: 100V	17c		2SD2092, (2SD1273A, 2SD2156A)
2SC3853	Si-N	NF/S-L, 120V, 6A, 60W, 20MHz	18j	Sak	BD245D, BD545D, 2SD718, 2SD896, ++
2SC3854	Si-N	NF/S-L, 160V, 8A, 80W, 20MHz	18j	Sak	BD245D, 2SD751
2SC3855	Si-N	NF/S-L, 200V, 10A, 100W, 20MHz	18j	Sak	BD245F, 2SC3263
2SC3856	Si-N	NF/S-L, 200V, 15A, 130W, 20MHz	18j	Sak	BD249F, 2SC3263
2SC3857	Si-N	NF/S-L, 200V, 15A, 150W, 20MHz	20j	Sak	2SC2773..2774, 2SC3370, 2SD846
2SC3856	Si-N	NF/S-L, 200V, 17A, 200W, 20MHz	20j	Sak	2SC2774, 2SC3264
2SC3859	Si-N+R	=2SC3860: SMD	35a	Say	KSR1110
2SC386(A)	Si-N	VHF, 20V, 0,02A, 500(A=600)MHz	7c	Tos	BF198..199, BF224..225, BF505, ++
2SC3860	Si-N+R	S, 50V, 0,1A, 0,3W, 250MHz, Rb=10kΩ	40c	Say	AA1A4Z, DTC114TS, RN1011, UN4215, ++
2SC3861	Si-N	UHF, 10V, 0,01A, 0,07W, 4GHz	7f	Mat	2SC2499, 2SC2570(A), 2SC3512
2SC3862	Si-N	SMD, TV-UHF-Tuner, 30V, 0,05A, 2400MHz	35d	Tos	—
2SC3863	Si-N+R	=2SC3864: SMD	35a	Say	—
2SC3864	Si-N+R	S, Rb=2,2k, Rbe=10k, 50V, 0,1A, 0,3W, 250MHz	40c	Say	DTC123YS, UN421H
2SC3865	Si-N	S-Reg, 500/400V, 5A, 40W, <500/1650ns	17c	Fjd	2SC3497, 2SC3570, 2SC3573, 2SC4054, ++
2SC3866	Si-N	S-L, 900/800V, 3A, 40W, <1000/4600ns	17c	Fjd	2SC3559, 2SC4303
2SC3867	Si-N	SMD, UHF, 20V, 0,05A, 3800MHz	35d	Hit	—
2SC3868	Si-N	S-L, 500/400V, 1,5A, 25W, <700/2300ns	17c	Mat	2SC3309, 2SC3560..61, 2SC4421
2SC3869	Si-N	S-L, 500/400V, 5A, 35W, <700/2300ns	17c	Mat	2SC3497, 2SC3570, 2SC3573, 2SC4054, ++
2SC387(A,G,GTM)	Si-N	UHF, 20V, 0,05A, 900(A=1200)MHz	7c	Tos	BF377..378, BF689K, BF763, 2SC2570, ++
2SC3870	Si-N	S-L, 500/400V, 7A, 40W, <700/2300ns	17c	Mat	2SC3571, 2SC3574, 2SC4130, 2SC4161, ++
2SC3871	Si-N	S-L, 500/400V, 10A, 45W, <700/2300ns	17c	Mat	2SC3572, 2SC3575, 2SC4162, 2SD1795, ++
2SC3872	Si-N	S-L, 500/400V, 10A, 70W, <700/2300ns	18c	Mat	2SC4296..97, 2SC4423
2SC3873	Si-N	S-L, 500/400V, 12A, 100W, <700/2300ns	16c	Mat	2SC4297, 2SC4423
2SC3874	Si-N	S-L, 500/400V, 15A, 150W, <700/2300na	77j	Mat	2SC3714
2SC3875	Si-N				—
2SC3876	Si-N	SMD, Uni, 35V, 0,5A, 300MHz	35b	Kec	—
2SC3877	Si-N	SMD, Uni, ra, 120V, 0,1A, 100MHz	35b	Kec	—
2SC3878	Si-N	SMD, Uni, ra, 35V, 0,1A, 120MHz	35b	Kec	—
2SC3879	Si-N	SMD, FM-ZF, 35V, 0,05A, 175MHz	35b	Kec	—
2SC388(A,ATM)	Si-N	TV-ZF, 20(A=25)V, 0,02A, 450MHz	7c	Tos	BF198..199, BF224..225, BF505, ++
2SC3880	Si-N	SMD, FM/VHF, 40V, 0,02A, 550MHz	35b	Kac	—
2SC3881	Si-N	SMD, FM/VHF, 30V, 0,05A, 600MHz	35b	Kec	—
2SC3883	Si-N+Di+Rbe=50	TV-HA, 1500/800V, 5A, 50W	18c	Hit	BU508D, BU706D, 2SC3481, 2SC4291, ++
2SC3864	Si-N	SN, HA, hi-res, 1400/600V, 8A, 50W	18c	Tos	2SC3894, (BU508AF, 2SD1546, 2SD1656)
2SC3884A	Si-N	=2SC3684: 1500/600V	18c		2SC3894, (BU508AF, 2SD1546, 2SD1656)
2SC3885	Si-N	SN, HA, hi-res, 1400/600V, 7A, 50W	18c	Tos	2SC3895, (BU508AF, 2SD1547)
2SC3885A	Si-N	=2SC3685: 1500/600V	18c		2SC3894, (BU508AF, 2SD1547)
2SC3866	Si-N	SN, HA, hi-res, 1400/600V, 6A, 50W	18c	Tos	2SC3896, (BU506AF)
2SC3886A	Si-N	=2SC3886: 1500/600V	18c		2SC3894, (BU506AF)
2SC3867	Si-N	=2SC3864: 80W	77c,j	Tos	2SC3486, (BU508A, BU708, BU908, ++)
2SC3866	Si-N	=2SC3885: 60W	77c,j	Tos	2SC3666, (BU506A, BU908, 2SD1498)
2SC3869	Si-N	=2SC3886: 60W	77c,j	Tos	2SC3887, (BU508A, BU908, 2SD1498)
2SC369	Si-N	VHF, 20V, 0,02A, 500MHz	5q	Tos	BF199, BF224, BF310, BF314, BF505++
2SC3890	Si-N	S-Reg, 500/400V, 7A, 30W, <1000/3500ns	17c	Sak	2SC3571, 2SC3573, 2SC4130, 2SC4161, ++
2SC3891	Si-N+Di	=2SC3864: int. Damper-Diode	18c	Tos	(2SC3681)
2SC3892	Si-N+Di	=2SC3885: int. Damper-Diode	18c	Tos	(2SC3682)

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2SC3892A	Si-N+Di	=2SC3885A: int. Damper-Diode	18c		(2SC3682)
2SC3893	Si-N+Di	=2SC3888: int. Damper-Diode	18c	Tos	(2SC3683)
2SC3893A	Si-N+Di	=2SC3886A: int. Damper-Diode	18c		(2SC3683)
2SC3894	Si-N	HA, hi-def, 1500/800V, 6A, 60W	18c	Say	2SC3884A..85A, (BU508AF)
2SC3895	Si-N	HA, hi-def, 1500/800V, 7A, 60W	18c	Say	2SC3685A, (BU508AF)
2SC3896	Si-N	HA, hi-def, 1500/800V, 8A, 70W	18c	Say	2SC3886A, (BU508AF)
2SC3897	Si-N	HA, hi-def, 1500/800V, 10A, 70W	18c	Say	(2SC3688, 2SC4589)
2SC3896	Si-N+R	=2SC3899: SMD	35a	Say	FA114Z, DTC144TK, KSR1112, UN2210
2SC3899	Si-N+R	S, 50V, 0,1A, 0,3W, 250MHz, Rb=47kΩ	40c	Say	AA114Z, DTC144TS, KSR1012, UN4210
2SC39(A)	Si-N	HF, 25V, 0,05A, 0,25W, 350..500MHz	2a	Fui	BF196..199, BF224..225, BF505,++
2SC390(D)	Si-N	VHF/UHF, 30V, 0,02A, 1000MHz	5q	Tos	BF377..378, BF689, BF763, 2N2857,++
2SC3900	Si-N+R	=2SC3901: SMD	35a	Say	FA113Z, DTC143TK, RN1410, UN2218,++
2SC3901	Si-N+R	S, 50V, 0,1A, 0,3W, 250MHz, Rb=4,7kΩ	40c	Say	AA113Z, DTC143TS, RN1010, UN4216,++
2SC3902	Si-N	TV-NF-E, 180/160V, 1,5A, 10W, 120MHz	14b	Say	(2SC3117, 2SD669)
2SC3903	Si-N	UHF, 15V, 65mA, 0,15W, 8,5GHz	25q	Mat	2SC3584
2SC3904	Si-N	=2SC3903: SMD	35a	Mat	2SC3583
2SC3905	Si-N	S-L, 100V, 15A, 60W, <300/1800ns	18c	Nec	(BD545C, BD745C)
2SC3906					—
2SC3906K	Si-N	=2SC3906:	35a		2SC3324, 2SC4050
2SC3907	Si-N	HiFi-NF-E, 180V, 12A, 130W, 30MHz	18j	Tos	2SC3263, 2SC3856
2SC3906	Si-N	AM-L, 50V, 25A, PQ=120W(30MHz)	57s	Mit	—
2SC3909	Si-N	S-L, 900/800V, 5A, 100W, <1000/4500ns	18j	Sak	BUW11A, BUV89, 2SC3153, 2SC3232,++
2SC391	Si-N	VHF/UHF, 20V, 0,02A, 1200MHz	5q	Tos	BF377..378, BF689, BF763, 2N2857,++
2SC3910	Si-N	S-L, 800/500V, 15A, 150W, <1000/4000ns	77j	Mat	2SC3993
2SC3912	Si-N+R	=2SC3916: SMD	35a	Say	DTD114EK, UN2223
2SC3913	Si-N+R	=2SC3917: SMD	35a	Say	DTD143EK, UN2222
2SC3914	Si-N+R	=2SC3918: SMD	35a	Say	DTD123YK, UN2224
2SC3915	Si-N+R	=2SC3919: SMD	35a	Say	DTD123EK, UN2221
2SC3918	Si-N+R	S, Rb=Rbe=10kΩ, 50V, 0,5A, 0,3W, 250MHz	40c	Say	DTD114ES, RN1224, UN4223, 2SC3920
2SC3917	Si-N+R	S, Rb=Rbe=4,7kΩ, 50V, 0,5A, 0,3W, 250MHz	40c	Sav	DTD143ES, RN1223, UN4222, 2SC3921
2SC3918	Si-N+R	S, Rb=2,2k, Rbe=10k, 50V, 0,5A, 0,3W, 250MHz	40c	Say	DTD123YS, RN1227, UN4224, 2SC3922
2SC3919	Si-N+R	S, Rb=Rbe=2,2kΩ, 50V, 0,5A, 0,3W, 250MHz	40c	Sav	DTD123ES, RN1222, UN4221, 2SC3923
2SC392(A)	Si-N	VHF/UHF-re, 30V, 0,02A, 800(A=>800)MHz	5g	Tos	BF377..378, BF689, BF763, 2N2857,++
2SC3920	Si-N+R	=2SC3916: 0,8W	7c	Say	→2SC3916
2SC3921	Si-N+R	=2SC3917: 0,8W	7c	Say	→2SC3917
2SC3922	Si-N+R	=2SC3918: 0,6W	7c	Say	→2SC3918
2SC3923	Si-N+R	=2SC3919: 0,8W	7c	Say	→2SC3919
2SC3924	Si-N	S-L, 900/800V, 3A, 30W, <1000/4000ns	15c	Hit	BUT11AF, 2SC3749, 2SC3559, 2SD1571,++
2SC3925	Si-N	Dual, UHF, SS, 20V, 0,1A, 5GHz		Say	—
2SC3926	Si-N	SMD, UHF, 20V, 0,03A, 4GHz	35a	Tos	BJQ29, BFQ81, BFR93, BFT75
2SC3927	Si-N	S-L, 900/550V, 10A, 120W, <1000/5500ns	18j	Sak	BUV47A, BUW12A, 2SC3637
2SC3928	Si-N	SMD, Uni, 50V, 0,1A, 200MHz	35a	Mit	BC846..847, BCW71..72, BCW81,++
2SC3929	Si-N	=2SC2405:	35a(2mm)	Mat	2SC4098
2SC3929A	Si-N	=2SC2405A:	35a(2mm)		—
2SC393	Si-N	TV-ZF, 20V, 0,02A	5g	Tos	BF198..199, BF224..225, BF505,++
2SC3930	Si-N	=2SC2295:	35a(2mm)	Mat	—
2SC3931	Si-N	=2SC2404:	35a(2mm)	Mat	—
2SC3932	Si-N	=2SC2460:	35a(2mm)	Mat	—
2SC3933	Si-N	=2SC3077:	35a(2mm)	Mat	—
2SC3934	Si-N	=2SC3110:	35a(2mm)	Mat	—
2SC3935	Si-N	=2SC3130:	35a(2mm)	Mat	—
2SC3936	Si-N	=2SC2778:	35a(2mm)	Mat	—
2SC3937	Si-N	=2SC3704:	35a(2mm)	Mat	—
2SC3938	Si-N	=2SC3757:	35a(2mm)	Mat	—
2SC3939	Si-N	Uni, 60V, 0,5A, 1W, 120MHz	7c(9mm)	Mat	2SC2235, 2SD667, 2SD1211, 2SD1937,++
2SC394	Si-N	AM/FM-V/M, 35V, 0,1A, 200MHz	7c	Tos	BF240..241, BF254..255, BF594..595,++
2SC3940	Si-N	Uni, 30V, 1A, 1W, 200MHz	7c(9mm)	Mat	2SC2236, 2SC3226, 2SD1207, 2SD1331,++
2SC3940A	Si-N	=2SC3940: 60V	7c(9mm)	Mat	2SD663, 2SD1014, 2SD1148, 2SD1207,++
2SC3941	Si-N	Vid, 300/300V, 0,07A, 1W, 80MHz	7c(9mm)	Mat	BF420A, 2SC3249, 2SC3458..69, 2SC4186
2SC3942	Si-N	CTV-Chroma, 300/300V, 0,1A, 10W, 140MHz	17c	Mat	2SC3585, 2SC4075
2SC3943	Si-N	=2SC3610: Iso, 8W	17c	Mat	(2SC3782)
2SC3944	Si-N	NF/HF-L, 150/150V, 1A, 15W, 200MHz	17c	Mat	—
2SC3944A	Si-N	=2SC3944: 180/180V	17c		—
2SC3945	Si-N	CTV-Vid-E, 300/300V, 0,1A, 10W, 100MHz	17c	Mat	2SC3565, 2SC4075, (2SC1505..07,++)
2SC3946	Si-N	CTV-Vid-E, 350/300V, 0,2A, 15W, >50MHz	17c	Mat	—
2SC3947	Si-N	S-L, 850/500V, 5A, 70W, <500/3300ns	18c	Fui	BUW11(A)F, 2SC4300, 2SC4428, 2SC4586

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2SC3948	Si-N	S-L, 850/500V, 10A, 75W, <500/3300ns	18c	Fui	2SC4199, (BUV47(A), BUW12(A), 2SC3637)
2SC3949	Si-N	S-L, 850/500V, 15A, 80W, <500/3300ns	18c	Fui	(BUV48(A), BUW13(A), 2SC3638)
2SC395	Si-N	S, 20V, 0,2A, 0,3W, 600MHz, 20/40ns	2a	Tos	BSS 11..12, BSY 17..18, 2N2368..69(A), ++
2SC3950	Si-N				—
2SC3951	Si-N	Vid-E, hi-def, 80V, 0,3A, 8W, 600MHz	14b	Say	(2SC3596)
2SC3952	Si-N	Vid-E, hi-def, 80V, 0,5A, 10W, 700MHz	14b	Say	(2SC3597)
2SC3953	Si-N	Vid-E, hi-def, 120V, 0,2A, 8W, 400MHz	14b	Say	(2SC3598)
2SC3954	Si-N	Vid-E, hi-def, 120V, 0,3A, 8W, 400MHz	14b	Say	(2SC3599)
2SC3955	Si-N	Vid-E, hi-def, 200V, 0,1A, 7W, 300MHz	14b	Say	(2SC3600)
2SC3956	Si-N	Vid-E, hi-def, 200V, 0,2A, 7W, 300MHz	14b	Say	(2SC3601)
2SC3957	Si-N-Darl	SMD, 40V, 0,3A, 100MHz, B>2000	44d(C)	Hit	—
2SC3956	Si-N	S-L, 150/60V, 5A, 30W, <600/3100ns	17j	Unz	BUW84(A..C), 2SD772(A,B)
2SC3959	Si-N	=2SC3956: 150/80V	17j	Unz	BUW64(A..C), 2SD772(A,B)
2SC395A	Si-N	=2SC395: 0,5A, 400MHz	2a		BSS 10, BSX 28, BSX 28, BSX 39, 2N3261
2SC396	Si-N	HF/S, 40V, 0,2A, 0,3W, 450MHz	2a	Tos	BSS 11, BSX 19..20, 2N2368..69(A), ++
2SC3960	Si-N	=2SC3958: 150/100V	17j	Unz	BUW64(A..C), 2SD772(A,B)
2SC3961	Si-N	S-L, 500/400V, 5A, 40W, <1000/3300ns	17j	Unz	BUT 11(A), BUV46(A), 2SC3497, ++
2SC3962	Si-N	S-L, 500/400V, 5A, 40W, <500/1900ns	17j	Unz	BUT 11(A), BUV46(A), 2SC3497, ++
2SC3963	Si-N	CTV, NF-E, 200/160V, 0,2A, >50MHz	14b	Tos	2SC3956, 2SC4564, 2SC4623, (BF 415)
2SC3964	Si-N	NF-E, hi-beta, 40V, 2A, 220MHz, B>500	14b	Tos	(2SD1694)
2SC3965	Si-N	NF, Vid, 300/300V, 0,1A, 1W, 140MHz	7c(9mm)	Mat	BF 420A, 2SC3249, 2SC3468..69, 2SC4168
2SC3966	Si-N	UHF, 30V, 0,02A, 0,2W, 1500MHz	25p	Mat	2SC2360, 2SC2464, 2SC2466, 2SC2728, ++
2SC3967	Si-N	=2SC3968 SMD	35a	Mat	BF 517, BFS 17, 2SC3016, 2SC3161, ++
2SC3968	Si-N	S-L, 400/400V, 2A, 20W, <1000/3500ns	17j	Rhm	TIP 75C, 2SC2333, 2SC2738, 2SC3169, ++
2SC3969	Si-N	=2SC3968: Iso	17c	Rhm	2SC3309, 2SC3560..81, 2SC4421
2SC397(D)	Si-N	VHF/UHF, 20V, 0,05A, 800(D=>400)MHz	5g	Tos	BF 377..378, BF 689, BF763, 2N2857, ++
2SC3970	Si-N	S-L, 800/500V, 1,5A, 25W, <1/3,3µs	17c	Mat	BUX84F..85F, 2SC3352, 2SD1571, ++
2SC3970A	Si-N	=2SC3970: 900/500V	17c		BUX85F, 2SC3794A, 2SC3978, 2SC4304, ++
2SC3971	Si-N	S-L, 800/500V, 3A, 30W, <1/3,3µs	17c	Mat	BUT 11(A)F, 2SC3749, 2SC4304, 2SD1571, ++
2SC3971A	Si-N	=2SC3971: 900/500V	17c		BUT 11AF, 2SC3559, 2SC4304, 2SC4517, ++
2SC3972	Si-N	S-L, 800/500V, 5A, 40W, <1/3,3µs	17c	Mat	BUT 11(A)F, BUT 18(A)F, 2SC3353, 2SC3750
2SC3972A	Si-N	=2SC3972: 900/500V	17c		BUT 11AF, BUT 18F, 2SC3795A, 2SC4518
2SC3973	Si-N	S-L, 800/500V, 7A, 45W, <1/3,3µs	17c	Mat	BUT 12(A)F, (BUT 54, BUT 56(A))
2SC3973A	Si-N	=2SC3973: 900/500V	17c		BUT 12AF, (BUT 56A)
2SC3974	Si-N	S-L, 800/500V, 7A, 80W, <1/3,3µs	18c	Mat	2SC4429, (BUV47(A), BUW 12(A), 2SC3449, ++)
2SC3975	Si-N	S-L, 800/500V, 10A, 100W, <1/3,3µs	16c	Mat	BUW13(A)F, 2SC4199, 2SC4459
2SC3978	Si-N	S-L, 800/500V, 12A, 150W, <1/3,3µs	17j	Mat	2SC3307, 2SC3910
2SC3977	Si-N	S-L, 900/800V, 1A, 30W, <700/2800ns	17c	Mat	BUX85F, 2SC3751, 2SC4231, 2SC4234
2SC3977A	Si-N	=2SC3977: 1000/800V	17c		BUX85F, 2SC3751, 2SC4231, 2SC4234
2SC3978	Si-N	S-L, 900/800V, 2A, 35W, <700/2800ns	17c	Mat	BUX85F, 2SC3752, 2SC4231, 2SC4234
2SC3978A	Si-N	=2SC3978: 1000/600V	17c		BUX85F, 2SC3752, 2SC4231, 2SC4234
2SC3979	Si-N	S-L, 900/800V, 3A, 40W, <700/2900ns	17c	Mat	BUT 11AF, 2SC3752, 2SC4234
2SC3979A	Si-N	=2SC3979: 1000/600V	17c		BUT 11AF, 2SC3752, 2SC4234, 2SC4517A
2SC398	Si-N	VHF-V, 20V, 0,02A, >250MHz	5q	Tos	BF225, BF 310, BF 314, BF502, BF507++
2SC3980	Si-N	S-L, 900/800V, 4A, 70W, <700/2800ns	18c	Mat	BUW11AF, 2SC4300, 2SC4457
2SC3960A	Si-N	=2SC3980: 1000/600V	18c		BUWF413311AF, 2SC4427
2SC3981	Si-N	S-L, 900/800V, 5A, 80W, <700/2600ns	18c	Mat	BUW 11AF, 2SC4300, 2SC4568
2SC3961A	Si-N	=2SC3981: 1000/800V	18c		BUW11AF, 2SC4427..28, 2SC4564
2SC3982	Si-N	S-L, 900/800V, 10A, 150W, <700/3300ns	77j	Mat	—
2SC3982	Si-N	=2SC3982: 1000/800V	77j		—
2SC3963	Si-N	Uni, 80V, 0,15A, 0,3W, 180MHz	7c	Rhm	BC174, BC182, BC190, BC546, ++
2SC3964	Si-N	=2SC3963:	9c	Rhm	BC174, BC162, BC190, BC546, ++
2SC3985	Si-N-Darl+Di	Z-Di(C→B), 50V, 1,2A, 15W, 180MHz, B=4k	17c(H)	Say	—
2SC3966	Si-N-Darl+Di	Z-Di(C→B), 50V, 2A, 15W, 180MHz, B=4k	17c(H)	Say	—
2SC3987	Si-N-Darl+Di	Z-Di(C→B), 50V, 3A, 15W, 180MHz, B=4k	17c(I)	Say	—
2SC3988	Si-N	S-L, 800/500V, 25A, 150W, <500/3300ns	18j	Say	BUX98P
2SC3989	Si-N	S-L, 800/500V, 25A, 200W, <500/3300ns	77j	Say	2SD1313
2SC399	Si-N	VHF-M, 20V, 0,02A, >250MHz	5q	Tos	BF 224, BF503, BF 505, BF 507, 2SC3136+
2SC3990	Si-N	S-L, 800/500V, 35A, 250W, <500/3300ns	77j	Say	—
2SC3991	Si-N	S-L, 800/500V, 50A, 300W, <500/3300ns	77j	Say	—
2SC3992	Si-N	S-L, 1100/600V, 12A, 200W, <500/3300ns	77j	Say	2SC3736, 2SC4096
2SC3993	Si-N	S-L, 1100/800V, 16A, 250W, <500/3300ns	77j	Say	—
2SC3994	Si-N	S-L, 1100/800V, 25A, 300W, <500/3300ns	77j	Say	—
2SC3995	Si-N	HA, hi-def, 1500/800V, 12A, 180W	77j	Say	—
2SC3998	Si-N	HA, hi-def, 1500/600V, 15A, 180W	77j	Say	—
2SC3997	Si-N	HA, hi-def, 1500/800V, 20A, 250W	77j	Say	—

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2SC3998	Si-N	HA, hi-def, 1500/800V, 25A, 250W	77j	Say	2SC4789
2SC3999	Si-N	Vid-E, 300V, 0,1A, 0,75W, 300MHz	7c	Nec	BF299, BF393, BF420A, 2SD1350,++
2SC40	Si-N	=2SC39: 750MHz	2a	Fui	BF198..199, BF224..225, BF505,++
2SC400(D,M)	Si-N	Uni, 30(D=35)V, 0,1A, 0,25W, 300MHz	2a	Tos, Mic	BC168, BC183, BC238, BC548, 2N3904++
2SC4000	Si-N	=2SC3999: 1W	9b	Nec	BF393, BF420A, MPS-A42, 2SD1350,++
2SC4001	Si-N	=2SC3999: 1,3W	14h	Nec	BF417, BF459, 2SC2621, 2SC3503, ++
2SC4002	Si-N	S, Tr, 400/400V, 0,2A, 0,6W, 70MHz	7c	Say	MPS-A44..45, 2SD1350
2SC4003	Si-N	=2SC4002: 10W	30j	Say	2SC3129, 2SC3588
2SC4004	Si-N	S-L, 900/800V, 1A, 30W, <1/4µs	17c	Mal	BUX85F, 2SC3751, 2SC4231
2SC4005	Si-N-Darl+Di	+Z-Di, 42V, 2A, 15W, 180MHz, B=4000	15c(I)	Say	—
2SC4006	Si-N-Darl+Di	+Z-Di, 42V, 3A, 20W, 180MHz, B=4000	15c(I)	Say	—
2SC4007	Si-N	NF/S-L, 100V, 4A, 40W, 10MHz	17j	Rhm	BD243C, BD539C, BD953, 2SD726, ++
2SC4006	Si-N	=2SC4007: Iso, 30W	17c	Rhm	2SC3691, 2SD1586, (BD243C, BD539C,++)
2SC4009	Si-N-Darl	Uni, 40V, 0,3A 0,3W, 200MHz, B=100000	9c	Rhm	BC517, MPS-A25..27
2SC401	Si-N	Uni, 50V, 0,1A, 0,1W, 170MHz, -/850ns	10b	Son	BC167, BC182, BC237, BC547, 2SD767++
2SC4010	Si-N	=2SC2021M: Pins=14mm	9c	Rhm	→2SC1740
2SC4011	Si-N	=2SC2063M: Pins=14mm	9c	Rhm	→2SC2058
2SC4012	Si-N	=2SC3078M: Pins=14mm	9c	Rhm	→2SC3078
2SC4013	Si-N	=2SC3079M: Pins=14mm	9c	Rhm	→2SC3079
2SC4014	Si-N	=2SC3080M: Pins=14mm	9c	Rhm	→2SC3080
2SC4015	Si-N	=2SC3270M: Pins=14mm	9c	Rhm	→2SC3270
2SC4016	Si-N	=2SC1652: Pins=14mm, 0,4W	9c	Rhm	→2SC1652
2SC4017	Si-N-Darl	=2SC1545: Pins=14mm	7c(C)	Rhm	→2SC1545
2SC4018K	Si-N	SMD, Uni, 50V, 0,1A, 230MHz	35a	Rhm	BC846..847, BCW71..72, BCW81,++
2SC4019	Si-N	Vid-L, 300/220V, 0,1A, 10W, 90MHz	30j	Mit	2SC2824, 2SC3406, 2SC3408, (BF758,++)
2SC402(A,B)	Si-N	Uni, 50V, 0,1A, 0,1..0,3W, 140..170MHz	10b	Son	BC167, BC182, BC237, BC547, 2SD767++
2SC4020	Si-N	S-Reg, 900/800V, 3A, 50W, <1/6µs	17j	Sak	BUT11A, BUV46A, 2SC3150, 2SC3490, ++-
2SC4021	Si-N	S-L, 1500/800V, 3A, 100W, -/4,8µs	18j	Sak	BUV71, 2SC4022
2SC4022	Si-N	S-L, 1500/800V, 6A, 120W, -/4,8µs	18j	Sak	BUV71, 2SC4023
2SC4023	Si-N	S-L, 1500/800V, 10A, 130W, -/4,8µs	18j	Sak	BUV71
2SC4024	Si-N	hi-beta, lo-sat, hi-Ueb, 100V, 10A, 35W	17c	Sak	(2SC4554)
2SC4026	Si-N	S-L, 500/400V, 5A, 35W, <700/2300ns	17c	Mal	2SC3570, 2SC3573, 2SC4054, 2SC4073, ++
2SC4027	Si-N	NF/S-L, 180V, 1,5A, 15W, 120MHz	30j	Say	2SD1033, 2SD1080..1082
2SC4028	Si-N	S-L, 1400/800V, 10A, 100W, <1/5µs	18j	Tos	BUV71, 2SC4023
2SC4029	Si-N	NF-HiFi-E, 230/230V, 15A, 150W, 30MHz	77j	Tos	—
2SC402S	Si-N	=2SC402: 80V	10b		BC546, 2SC1775(A), 2SC2240, 2SC3245, ++
2SC403(A,B,C)	Si-N	Uni, 50..80V, 0,1A, 0,1W, 140..170MHz	10b	Son	BC174, BC182, BC190, BC546, 2SD767++
2SC4030	Si-N	S, 1700/900V, 0,05A, 1,2W, 6MHz	30c	Say	—
2SC4031	Si-N	S, 2000/900V, 0,02A, 1,2W, 6MHz	30c	Say	—
2SC4032	Si-N-Darl	=2SC1545: Pins=14mm	9c	Rhm	→2SC1545
2SC4033	Si-N	Uni, 130V, 0,03A, 0,15W, 80MHz	9c	Rhm	2SC2362K, 2SC2375, 2SC3245A, 2SC3800, ++
2SC4034	Si-N	Uni, 80V, 0,05A, 0,15W, 140MHz	9c	Rhm	BC546, 2SC1890(A), 2SC2675, 2SD1512, ++
2SC4035	Si-N	=2SC1614: Pins=14mm	9c	Rhm	→2SC1614
2SC4038	Si-N	=2SC1615: Pins=14mm	9c	Rhm	→2SC1615
2SC4037	Si-N	=2SC1652: Pins=14mm	9c	Rhm	→2SC1652
2SC4038	Si-N	=2SC2021: Pins=14mm	9c	Rhm	→2SC1740
2SC4039	Si-N	=2SC2063: Pins=14mm	9c	Rhm	→2SC2058
2SC404	Si-N	Uni, 50V, 0,05A, 0,1W, 170MHz	10b	Son	BC167, BC182, BC237, BC547, 2SD767++
2SC4040	Si-N	=2SC2673: Pins=14mm	9c	Rhm	→2SC2673
2SC4041	Si-N	=2SC3080: Pins=14mm	9c	Rhm	→2SC3080
2SC4042(S)	Si-N	UHF, 30V, 0,05A, 0,15W, 1500MHz	7c, 41c	Rhm	BF377..378, BF357, BF630, 2SC2570, ++
2SC4043(S)	Si-N	UHF, 20V, 0,05A, 0,15W, 3200MHz	7c, 41c	Rhm	2SC2498..99, 2SC2570, 2SC3776..77
2SC4044	Si-N	UHF, 30V, 0,05A, 0,15W, 2000MHz	7c	Rhm	BF630, 2SC2498..99, 2SC2570, 2SC3776..77
2SC4045	Si-N	UHF, 20V, 0,05A, 0,15W, 3200MHz	9c	Rhm	2SC2498..99, 2SC2570, 2SC3776..77
2SC4046	Si-N	NF/HF-L, 120/120V, 0,2A, 8W, 350MHz	14h	Hit	—
2SC4047	Si-N+R	=2SC4048: SMD	35a	Say	FA1A4P, DTC114YK, RN1407, UN2214,++
2SC4048	Si-N+R	S, 50V, 0,1A, 0,2W, Rb=10kΩ, Rbe=47kΩ	40c	Say	AA1A4P, DTC114YS, RN1007, UN4214,++
2SC4049	Si-N+R	=2SC4048:	40f	Say	→2SC4048
2SC405	Ge-N	S, 25V, 0,2A, 0,15W, B=80	2a	Mit	ASY26..29, ASY73..75
2SC4050	Si-N	SMD, NF, 120/120V, 0,1A, 310MHz	35a	Hit	2SC1622A, 2SC3324
2SC4051	Si-N	S-L, 600/450V, 3A, 40W, <500/2200ns	17j	Shi	BUT11(A), BUT93, BUV46A, 2SC3086, ++
2SC4052	Si-N	=2SC4051: Iso, 25W	15c	Shi	BUT11(A)F, 2SC4054, 2SC4304, 2SD1571,++
2SC4053	Si-N	S-L, 600/450V, 5A, 50W, <500/2200ns	17j	Shi	BUT11(A), BUT18(A), BUV46(A), 2SC3047
2SC4054	Si-N	=2SC4053: Iso	15c	Shi	BUT11(A)F, 2SC3750, 2SC3795, 2SC4056, ++
2SC4055	Si-N	S-L, 600/450V, 8A, 80W, <500/2200ns	17j	Shi	BUT54, BUT56(A), MJE13006..07,++
2SC4058	Si-N	=2SC4055: Iso, 45W	15c	Shi	BUT12AF

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2SC4057	Si-N	=2SC4055: 80W	16j	Shi	BUV47(A), BUW12(A), 2SC3831, 2SC4157++
2SC4058	Si-N	S-L, 600/450V, 10A, 100W, <500/2200ns	16j	Shi	BUV48(A), BUW13(A), 2SC3451, 2SC3638++
2SC4059	Si-N	S-L, 600/450V, 15A, 130W, <500/2200ns	16j	Shi	BUV48(A), BUW13(A), 2SC3451, 2SC3638++
2SC406	Ge-N	=2SC405: B=120	2a	Mit	ASY28..29, ASY73..75
2SC4060	Si-N	S-L, 600/450V, 20A, 150W, <500/2200ns	16j	Shi	BUX98AP, 2SC3988
2SC4061K	Si-N	SMD, Vid, 300/300V, 0,1A, 100MHz	35a	Rhm	BFN26
2SC4062	Si-N-Darl+Di	L, 100V, 7A, 30W, 100MHz, B=800	17c	Nec	2SD1415, 2SD1590, 2SD1791, 2SD1830,++
2SC4063	Si-N-Darl+Di	L, 100V, 15A, 35W, 100MHz, B=800	17c	Nec	2SC4063
2SC4064	Si-N	lo-sat, 50V, 12A, 35W, 40MHz	17c	Sak	2SC3709..10, 2SD1669, (2SD1062)
2SC4065	Si-N+Di	=2SC4064: 60V, ±12A	17c	Sak	2SC3709..10, 2SD1669, (2SD1062)
2SC4066	Si-N+R	=2SC4067: SMD	35a	Say	DTC144GK
2SC4067	Si-N+R	S, 50V, 0,1A, 0,3W, 250MHz, Rbe=47kΩ	40c	Say	DTC144GS
2SC4068	Si-N	=2SC3966: SMD	35a(2mm)	Mat	—
2SC4069	Si-N+R	=2SC4070: SMD	35a	Say	DTC124GK
2SC407	Si-N	S-L, t50/100V, 10A, 100W, B>10	23a	Shi	BUW70, BUX17(A..C), BUY18, 2SC2944,++
2SC4070	Si-N+R	S, 50V, 0,1A, 0,3W, 250MHz, Rbe=22kΩ	40c	Say	DTC124GS
2SC4071	Si-N	Dual, 30V, 0,03A, 0,25W, 1200MHz		Say	—
2SC4072	Si-N	Dual, 25V, 0,05A, 0,25W, 3500MHz		Say	—
2SC4073	Si-N	S-Reg, 500/400V, 5A, 30W, <1/3,5µs	17c	Sak	BUT11(A)F, 2SC3570, 2SC3573, 2SC4054,++
2SC4074	Si-N	SMD, VHF/UHF, 30V, 0,05A, 1500MHz	35a	Rhm	BFR53, 2SC3014, 2SC3016
2SC4075	Si-N	CTV-NF/Vid, 300/300V, 0,2A, 10W, >50MHz	17c	Say	2SC3565, (2SC1505..07, 2SC1755..57,++)
2SC4076	Si-N	SMD, Uni, 60V, 0,15A, 180MHz	35a	Rhm	BC846, BCV71..72, 2SC3323
2SC4077	Si-N	NF, ra, 30V, 0,1A, 0,3W, 230MHz	7c	Rhm	BC169, BC164, BC239, BC549,++
2SC4078	Si-N	=2SC4077:	9c	Rhm	BC169, BC184, BC239, BC549,++
2SC4079	Si-N	=2SC4077: SMD	35a	Rhm	BC849..850, BCF32..33, BCF81,++
2SC408	Si-N	=2SC407: B>20	23a	Shi	BUW70, BUX17(A..C), BUY18, 2SC2944,++
2SC4060	Si-N	SMD, Vid, 200/200V, 0,1A, 400MHz	39b	Say	—
2SC4061	Si-N	=2SC2412K:	35a(2mm)	Rhm	2SC4128, 2SC4155
2SC4082	Si-N	=2SC3837K:	35a(2mm)	Rhm	—
2SC4063	Si-N	=2SC3838K:	35a(2mm)	Rhm	—
2SC4084	Si-N	=2SC3839K:	35a(2mm)	Rhm	—
2SC4085	Si-N	SMD, VHF/UHF, 30V, 0,02A, 1000MHz	44o	Nec	2SC4086..4087
2SC4086	Si-N	SMD, UHF, 30V, 0,05A, 2000MHz	44o	Nec	2SC4067
2SC4067	Si-N	SMD, UHF, 30V, 0,05A, 2000MHz	44o	Nec	2SC4066
2SC4088	Si-N	SMD, UHF, 15V, 5mA, 4000MHz	44o	Nec	2SC4089
2SC4089	Si-N	SMD, UHF, 25V, 0,03A, 4000MHz	44o	Nec	—
2SC409	Si-N	=2SC407: 200/140V	23a	Shi	BUX17(A..C), BUX42, BUY18, 2SC2944,++
2SC4090	Si-N	SMD, UHF, 30V, 0,05A, 2000MHz	44u	Nec	2SC4092
2SC4091	Si-N	SMD, UHF, 15V, 5mA, 4000MHz	44u	Nec	2SC4092
2SC4092	Si-N	SMD, UHF, 25V, 0,07A, 6000MHz	44u	Nec	2SC4093
2SC4093	Si-N	SMD, UHF, 20V, 0,1A, 8500MHz			—
2SC4094	Si-N	SMD, UHF, 20V, 0,065A, 9000MHz	44u	Nec	—
2SC4095	Si-N	SMD, UHF, 20V, 0,035A, 10GHz	44u	Nec	—
2SC4096	Si-N	S-L, 1400/800V, 10A, 150W, 1/3,8µs	17j	Mat	2SC3995
2SC4097	Si-N	=2SC2411K:	35a(2mm)	Rhm	2SD1949
2SC4098	Si-N	=2SC2413K:	35a(2mm)	Rhm	2SC4128, 2SC4155
2SC4099	Si-N	=2SC2059K:	35a(2mm)	Rhm	—
2SC41	Si-N	S-L, t50V, 5A, 50W, 20MHz, B>12	23a	Son	BD245D, 2N3442, 2SC2260..2262, 2SD73t,++
2SC4t0(A)	Si-N	=2SC407: 200/140(A=200/200)V, B>20	23a	Shi	BUXt7(A..C), BUX42, BUY18, 2SC2944,++
2SC4100	Si-N	=2SC3082K:	35a(2mm)	Rhm	—
2SC4101	Si-N	SMD, NF, ra, 120V, 0,05A, 140MHz	35a(2mm)	Rhm	2SC3324, 2SD8t4(A)
2SC4102	Si-N	=2SC3906K:	35a(2mm)	Rhm	—
2SC4103	Si-N	=2SC3902K:	35a(2mm)	Rhm	—
2SC4104	Si-N	SMD, Vid, 70V, 0,05A, 700MHz	35a	Say	—
2SC4105	Si-N	S-L, 500/400V, 4A, 40W, <500/2800ns	17j	Say	BUT11(A), TIP75C, 2SC3038, 2SC3497,++
2SC4106	Si-N	S-L, 500/400V, 7A, 50W, <500/2600ns	17j	Say	BUT54, BUT56(A), 2SC3170, 2SC4055,++
2SC4t07	Si-N	S-L, 500/400V, 10A, 60W, <500/2800ns	17j	Say	BUT76(A), BUV56(A), 2SC3562, 2SC4184,+
2SC4106	Si-N	S-L, 500/400V, 12A, 100W, <500/2800ns	18j	Say	BUV48(A..C), BUW13(A), 2SC3520, 2SC4140,+
2SC4109	Si-N	S-L, 500/400V, 18A, 140W, <500/2800ns	18j	Say	BUX98(A)P, 2SC3850
2SC411	Si-N	=2SC407: 300/200V	23a	Shi	BUX17A..C, BUX42, BUYt8, 2SC2626,++
2SC4110	Si-N	S-L, 500/400V, 25A, 160W, <500/2800ns	18j	Say	BUX96P
2SC4111	Si-N	S-L, 1500/700V, 10A, 150W, <1/12,6µs	17j	Mat	2SC3995
2SC4112	Si-N+R	=2SC4113: SMD	35a	Say	—
2SC4113	Si-N+R	S, 50V, 0,1A, 200MHz, Rb=2,2kΩ	40c	Say	—
2SC4114	Si-N	SMD, 600/550V, 0,1A, <2/5.5µs	39b	Mat	—
2SC4115(S)	Si-N	NF/S, 40V, 2A, 0,4W, 290MHz	41c	Rhm	2SC3225, 2SD1055, 2SD1227, 2SD2177,++

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2SC4116	Si-N	SMD, Uni, ra, 60V, 0,15A, >80MHz	35a(2mm)	Tos	—
2SC4117	Si-N	SMD, Uni, ra, 120V, 0,1A, 100MHz	35a(2mm)	Tos	2SC4101..4102
2SC4118	Si-N	SMD, Uni, 35V, 0,5A, 300MHz	35a(2mm)	Tos	2SC4097
2SC4119	Si-N-Darl+Di	S-L, 1500/800V, 15A, 250W, B>25	77j	Say	—
2SC412	Si-N	=2SC407: 300/200V, B>20	23a	Shi	BUX17AC, BUX42, BUY18, 2SC2626, ++
2SC4120	Si-N+R	=2SC4121: SMD	35a	Say	FA1F4Z, DTC124TK, KSR1111, UN2217
2SC4121	Si-N+R	S, 50V, 0,1A, 0,3W, 250MHz, Rb=22kΩ	40c	Say	AA1F4Z, DTC124TS, KSR1011, UN4217
2SC4122	Si-N+Di	HA, hi-def, 1500/800V, 6A, 60W	18c	Say	2SC4294, (BU508DF, 2SD1556, 2SD1852)
2SC4123	Si-N+Di	HA, hi-def, 1500/800V, 7A, 60W	18c	Say	(BU508DF)
2SC4124	Si-N+Di	HA, hi-def, 1500/800V, 6A, 70W	18c	Say	(BU508DF)
2SC4125	Si-N+Di	HA, hi-def, 1500/800V, 10A, 70W	18c	Say	(2SC3684)
2SC4126	Si-N	SMD, UHF, 15V, 0,05A, 6GHz	44u	Hit	2SC4092
2SC4127	Si-N	SMD, UHF, 15V, 0,05A, 7,5GHz	44u	Hit	2SC4094
2SC4128	Si-N	SMD, Uni, 50V, 0,1A, 230MHz	35a(2mm)	Rhm	2SC4081, 2SC4141
2SC4129	Si-N	S-L, 400/400V, 5A, 30W, <1/3,5µs	17c	Rhm	BUT11(A)F, 2SC3570, 2SC3573, 2SC4073, +
2SC413	Si-N	HF/S-L, 60V, 1,5A, 20W, 180MHz	2a	Oki	(BD137, BD228, BD377, 2SD1177..1178)
2SC4130	Si-N	S-L, 500/400V, 7A, 30W, <1/2,7µs	17c	Sak	2SC3571, 2SC3574, 2SC3890, 2SC4056, ++
2SC4131	Si-N	hi-Ueb, 100V, 15A, 60W, 0,5/2,4µs	18c	Sak	(BD545C, BD745C, 2SD1840)
2SC4132	Si-N	SMD, S, 120V, 2A, 60MHz	39b	Rhm	2SC3649, 2SD1420..1421
2SC4133	Si-N+R	S, 50V, 0,1A, 250MHz, Rb=4,7k, Rbe=47kΩ	40c	Say	DTC143ZS, KSR1014, RN1006, 2SC4195
2SC4134	Si-N	S-L, 120V, 1A, 10W, 120MHz	30j	Say	2SD1074..75, 2SD1283 84
2SC4135	Si-N	S-L, 120V, 2A, 15W, 120MHz	30j	Say	2SD1815..16
2SC4136	Si-N	S-L, 200/120V, 20A, 140W, <0,5/2µs	23a	Fjd	BUV11, BUW58, BUX11, 2SC2865(A), ++
2SC4137	Si-N	hi-beta, 25V, 0,1A, 400MHz, B>580	14b	Rhm	—
2SC4136	Si-N	S-Reg, 500/400V, 10A, 80W, <1/3,5µs	18j	Sak	BUV48(A..C), BUW13(A), 2SC3042, ++
2SC4139	Si-N	S-Reg, 500/400V, 15A, 120W, <1/3,5µs	18j	Sak	BUV48(A..C), BUW13(A), 2SC3520, ++
2SC414	Si-N	HF/S-L, 90V, 1,5A, 20W, 180MHz	2a	Oki	(BD139, BD230, BD379, 2SD1177..1178)
2SC4140	Si-N	S-Reg, 500/400V, 18A, 130W, <1/3,5µs	18j	Sak	BUX98AP, 2SC3850, 2SC4110
2SC4141	Si-N	SMD, Uni, 60V, 0,1A, 180MHz	35a(2mm)	Rhm	BC846, BCV71..72, 2SC3639, 2SC4116, ++
2SC4142	Si-N	TV-HA, 1500/800V, 5A, 50W	18c	Hit	BU506AF, 2SD1545 46, 2SD1655..56, ++
2SC4143	Si-N	TV-HA, 1500/800V, 5A, 50W	18c	Hit	BU508AF, 2SD1545 46, 2SD1655..56, ++
2SC4144	Si-N	TV-HA, 1300/500V, 6A, 50W	18c	Hit	BU506AF, BU908F, 2SD1548
2SC4145	Si-N	NF/S, 80V, 2A, 1,2W, <1/4µs	7c(9mm)	Rhm	2SC3328, 2SC3669, 2SD1015, 2SD2182
2SC4146	Si-N+R	=2SC4133: SMD	35A	Say	—
2SC4147	Si-N	HF/Vid-L, 300/300V, 0,1A, 5W, 100MHz	≈14h	Rhm	BF417, BF459, 2SC3417, 2SC3503, ++
2SC4148	Si-N	S-L, lo-sat, 60V, 7A, 25W, <300/2000ns	15c	Shi	2SC3747
2SC4149	Si-N	S-L, lo-sat, 60V, 10A, 25W, <300/2000ns	15c	Shi	2SC3748
2SC415	Si-N	HF/S-L, 120V, 1,5A, 20W, 160MHz	2a	Oki	(2SC2690(A), 2SC3117, 2SD669)
2SC4150	Si-N	S-L, lo-sat, 60V, 12A, 25W, <300/2000ns	15c	Shi	2SC3709, 2SC4085
2SC4151	Si-N	S-L, lo-sat, 60V, 15A, 30W, <300/2000ns	15c	Shi	2SC3694, 2SC4552
2SC4152	Si-N	S-L, 1400/700V, 0,3A, 20W, <2/4µs	17c	Mat	—
2SC4153	Si-N	S-L, 200/120V, 7A, 30W, <0,5/3,5µs	17c	Sak	2SD1792
2SC4154	Si-N	=2SC3052:	35a(2mm)	Mit	2SC4076, 2SC4116
2SC4155	Si-N	=2SC3926:	35a(2mm)	Mit	BC846..847, 2SC4081, 2SC4126, 2SC4141 ++
2SC4156	Si-N	Dual, 60V, 0,5A, 0,4W, 300MHz		Say	—
2SC4157	Si-N	S-L, 800V/450V, 10A, 100W, <0,5/3µs	18j	Tos	BUV47(A), BUW12(A), 2SC3831, ++
2SC4156	Si-N	Vid-E, 250/250V, 0,1A, 300MHz, 8W	17c	Mat	2SC3565, 2SC4075, (2SC1505..1507, ++)
2SC4159	Si-N	NF/S-L, 180/160V, 1,5A, 15W, 100MHz	17c	Say	2SC3298A,B
2SC416	Si-N	HF/S-L, 90V, 1,5A, 20W, 180MHz	2a	Oki	(BD139, BD230, BD379, 2SD1177..1178)
2SC4160	Si-N	=2SC4105: Iso, 25W	17c	Say	BUT11(A)F, 2SC3573, 2SC4054, 2SC4073, ++
2SC4161	Si-N	=2SC4108: Iso, 30W	17c	Say	2SC3571, 2SC3574, 2SC4056, 2SC4130, ++
2SC4162	Si-N	=2SC4107: Iso, 35W	17c	Say	2SC3562, 2SC3572, 2SC3575, 2SD1795, ++
2SC4163	Si-N	=2SC4108: Iso, 40W	17c	Say	—
2SC4164	Si-N	=2SC4108: 70W	17j	Say	BUV66(A), MJE13008..13009
2SC4165	Si-N	HF/Vid-L, 300/300V, 0,2A, 130MHz	14h	Hit	BF417, 2SC2621, (BF617, BF756..759)
2SC4166	Si-N	S/Vid, 400/400V, 0,1A, 0,9W, 20MHz	7c(9mm)	Rhm	2SC3489
2SC4167	Si-N	UHF-L, 35V, 2A, PQ=8W(520MHz)		Mit	—
2SC4166	Si-N	SMD, S, 40V, 0,15A, <40/205ns	35a	Say	—
2SC4169	Si-N-Darl+Di	+Z-Di(B→C), S, 50V, 1,2A, 1W, B=4000	7c(9mm)	Say	2SD1153, 2SD1609, 2SD1929, 2SD2026
2SC417..419	Si-N			Oki	—
2SC4170	Si-N	SMD, Dual-Emitter, 50V, 0,2A, 160MHz	44	Say	—
2SC4171	Si-N	S-L, 800/500V, 3A, 40W, <1/4µs	30c	Say	2SC4221, 2SC4599, (BUT11(A), 2SC3086, +)
2SC4172	Si-N	S-L, 800/500V, 5A, 50W, <1/4µs	30c	Say	2SC4222, 2SC4800, (BUT11(A), 2SC3047, +)
2SC4173	Si-N	SMD, S, 60V, 0,5A, 30/150ns	35a(2mm)	Nec	—
2SC4174	Si-N	SMD, HF/NF, 180/160V, 0,05A, 120MHz	35a(2mm)	Nec	BF820, BF822, BFN22
2SC4175	Si-N	SMD, S, 40V, 0,2A, <20/40ns	35a(2mm)	Nec	2SC4176

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2SC4176	Si-N	SMD, S, 40V, 0,2A, <12/18ns	35a(2mm)	Nec	—
2SC4177	Si-N	SMD, Uni, 60V, 0,1A, 250MHz	35a(2mm)	Nec	2SC4141
2SC4178	Si-N	SMD, FM, 30V, 0,02A, 600MHz	35a(2mm)	Nec	2SC3932, 2SC3935
2SC4179	Si-N	SMD, AM/FM, 50V, 0,05A, >150MHz	35a(2mm)	Nec	2SC3931, 2SC3936
2SC4180	Si-N	SMD, Uni, 120V, 0,05A, >50MHz	35a(2mm)	Nec	2SC4101..4102, 2SC4117
2SC4181(A)	Si-N	hi-beta, hi-Ueb, 80V, 0,15A, B>1000	35a(2mm)	Nec	—
2SC4182	Si-N	SMD, VHF/UHF-O, 30V, 0,05A, 900MHz	35a(2mm)	Nec	BF517W, BFS17W, 2SC3933, 2SC4780
2SC4183	Si-N	SMD, VHF/UHF-V, 30V, 0,02A, 900MHz	35a(2mm)	Nec	BFS17W, 2SC3933, 2SC4780
2SC4184	Si-N	SMD, VHF/UHF-V/M, 30V, 0,05A, 1500MHz	35a(2mm)	Nec	2SC5110, 2SC4780
2SC4185	Si-N	SMD, VHF/UHF-M, 30V, 0,05A, 1600MHz	35a(2mm)	Nec	2SC5110, 2SC4780
2SC4186	Si-N	SMD, VHF/UHF-O, 25V, 0,03A, 2000MHz	35a(2mm)	Nec	BFR93W, 2SC5110, 2SC4780
2SC4187	Si-N	SMD, VHF/UHF-V, 15V, 5mA, 3000MHz	35a	Nec	BF775, BFQ29, BFR35, 2SC3098
2SC4188	Si-N	Vid-E, hi-def, 200V, 0,1A, 10W, 150MHz	17j	Say	—
2SC4189	Si-N	SMD, Vid, 300/300V, 0,1A, 100MHz	39b	Rhm	BFN18, 2SC3380, 2SC3515, 2SC3554
2SC4190	Si-N	65V, 0,3A, >1500MHz	17c	Mat	—
2SC4191	Si-N	S-L, 500/400V, 2A, 20W, <1/3,5µs	17j	old	BUX84..85, TIP75C, 2SC2738, 2SC3189, ++
2SC4192	Si-N	S-L, 500/400V, 3A, 30W, <1/3,5µs	17j	old	BUT11(A), BUT83, TIP75C, 2SC4105, ++
2SC4193	Si-N	S-L, 500/400V, 5A, 40W, <1/3,5µs	17j	old	BUT11(A), BUV46(A), 2SC3497, ++
2SC4194	Si-N	S-L, 500/400V, 7A, 50W, <1/3,5µs	17j	old	BUT56(A), 2SC3170, 2SC4055, 2SC4106, ++
2SC4195	Si-N+R	=2SC4133:	40l	Say	→2SC4133
2SC4196	Si-N	SMD, UHF-O, 25V, 0,05A, 2400MHz	35a	Hit	BFT75, 2SC3014, 2SC3772..3773
2SC4197	Si-N	SMD, UHF-V/M, 25V, 0,05A, 3800MHz	35a	Hit	BF770A, BFT75, 2SC2845, 2SC3774
2SC4198	Si-N	hi-beta, 25V, 0,5A, 200MHz, B=820	14h	Rhm	—
2SC4199	Si-N	TV-HA/SMPS, 1400/800V, 10A, 100W	16c	Sak	BU2520AF, 2SC3897, 2SC4542, 2SD1548
2SC4199A	Si-N	=2SC4199: 1500/600V	18c		BU2520AF, 2SC3897, 2SC4542
2SC42	Si-N	=2SC41: B>4	23a	Son	BD245D, 2N3442, 2SC2260..2262, 2SD731 ++
2SC420	Si-N	Dual, 25V, 0,08A, 0,15W, <15/30ns	TO-80	Oki	—
2SC4200	Si-N	S, Vid-Tr, 20V, 0,6A, 5W, 2500MHz	14b	Tos	—
2SC4201	Si-N	S, Vid-E, 100V, 0,5A, 30W, 1100MHz	17o	Tos	—
2SC4202	Si-N	=2SC4201: 20W	17j	Tos	—
2SC4203	Si-N	S-L, Vid-E, hi-res, 180V, 0,5A, 10W, 400MHz	30j	Tos	—
2SC4204	Si-N	hi-Ueb, hi-beta, lo-sat, 30V, 0,7A, B>600	7c	Say	(2SC3070, 2SC3225, 2SC3673, 2SD1582)
2SC4205	Si-N	S-L, 400/400V, 5A, 40W, <1/3,5µs	17j	Rhm	BUT11(A), MJE53T, 2SC2827, 2SC3497, ++
2SC4206	Si-N	S-Reg, 900/600V, 6A, 80W, <1/4µs	18j	Fjd	BU903, BU428A, 2SC3536, 2SC3636, ++
2SC4207	Si-N	SMD, Dual, 80V, 0,15A, >80MHz	45	Tos	—
2SC4208	Si-N	Uni, 30V, 0,5A, 1W, 150MHz	7c(9mm)	Mat	BC635, 2SC2236, 2SD1146, 2SD1331, ++
2SC4208A	Si-N	=2SC4208: 80V	7c(9mm)		BC837, 2SC3328, 2SD1207, 2SD1635
2SC4209	Si-N	SMD, Uni, 80V, 0,3A, 100MHz	35a	Tos	BCW68, 2SD1782
2SC421..422	Si-N			Oki	—
2SC4210	Si-N	SMD, Uni, 35V, 0,8A, 120MHz	35a	Tos	BCW65..66, 2SD1782
2SC4211	Si-N	SMD, Uni, 55V, 0,15A, 200MHz	35a(2mm)	Say	BC848, BCV71..72, 2SC4141, 2SC4177, ++
2SC4212	Si-N	=2SC3948: 5W	14h	Mat	BF850, 2SC3418
2SC4213	Si-N	SMD, hi-Ueb, 50V, 0,3A, B=150(reverse)	35a(2mm)	Tos	—
2SC4214	Si-N	SMD, C4407TV-UHF-Tuner, 25V, 0,02A, 850MHz	44o	Tos	—
2SC4215	Si-N	SMD, VHF, 40V, 0,02A, 550MHz	35a(2mm)	Tos	BF599, BF799, BFS20, 2SC3374, ++
2SC4216	Si-N+R	=2SC3901:	40l	Say	→2SC3901
2SC4217	Si-N	S/Vid-E, hi-def, 300V, 0,2A, 70MHz	14b	Say	(BF417, BF756..759, 2SC2821, ++)
2SC4218	Si-N	Vid, 300/300V, 0,1A, 0,5W, 70MHz	7c	Say	BF299, BF420A, 2SC3486, ++
2SC4219	Si-N	S-L, 500/400V, 4A, 40W, <0,5/2,8µs	30c	Say	2SC4597
2SC4220	Si-N	S-L, 500/400V, 7A, 50W, <0,5/2,8µs	30c	Say	2SC4596
2SC4221	Si-N	S-L, 800/500V, 3A, 40W, <0,5/3,3µs	30c	Say	2SC4171, 2SC4599
2SC4222	Si-N	S-L, 800/500V, 5A, 50W, <0,5/3,3µs	30c	Say	2SC4172, 2SC4500
2SC4223	Si-N	S-L, 1100/600V, 1,5A, 40W, <0,5/3,3µs	30c	Say	2SC4601
2SC4224	Si-N	S-L, 1100/800V, 3A, 50W, <0,5/3,3µs	30c	Say	2SC4602
2SC4225	Si-N	SMD, VHF/UHF, -/12V, 0,07A, 4000MHz	35a	Nec	BFR108, 2SC3161, 2SC3774..75
2SC4226	Si-N	SMD, VHF/UHF, -/12V, 0,1A, 4500MHz	35a	Nec	BFR108, 2SC3775
2SC4227	Si-N	SMD, VHF/UHF, -/10V, 65mA, 7000MHz	35a	Nec	BFR193, 2SC3445, 2SC5084
2SC4228	Si-N	SMD, VHF/UHF, -/10V, 35mA, 8000MHz	35a	Nec	BFR183, 2SC3445, 2SC5064
2SC4229	Si-N	SMD, UHF, 30V, 0,02A, 1000MHz	35a	Hit	BF517, BFS17, 2SC3181, 2SC3099, ++
2SC423	Si-N	HF-A/Tr, 40V, 0,3A, 0,5W, 500MHz	2a	Say	BFR36, BFW16..17, BFX55
2SC4230	Si-N	S-L, 1200/800V, 2A, 50W, <0,5/3,8µs	17j	Shi	BU505, MJE8500, 2SC3178
2SC4231	Si-N	=2SC4230: 30W	15c	Shi	BU505F, 2SC4234, (MJE8500, 2SC3178)
2SC4232	Si-N	=2SC4230: 70W	16j	Shi	2SD1543, BU705, 2SC3483, 2SD1493..84
2SC4233	Si-N	S-L, 1200/800V, 3A, 60W, <0,5/3,8µs	17j	Shi	BU505, MJE8502, 2SC3050
2SC4234	Si-N	=2SC4233: 45W	15c	Shi	BU505F, (MJE8502, 2SC3050)
2SC4235	Si-N	=2SC4233: 80W	16j	Shi	BU708, 2SC3387, 2SC3642

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2SC4236	Si-N	S-L, 1200/800V, 6A, 100W, <0,5/3,8µs	16j	Shi	BUV89, 2SC3466, 2SC3643
2SC4237	Si-N	S-L, 1200/800V, 10A, 150W, <0,5/3,8µs	16j	Shi	BUV48B,C, 2SC3644, 2SC4023
2SC4238	Si-N	SMD, VHF, 30V, 0,05A, 1300MHz	35a	Mat	BFR53, 2SC3014, 2SC3016, 2SC4082
2SC4239	Si-N	SMD, UHF/ZF, 15V, 0,05A, 2000MHz	35a(2mm)	Mat	—
2SC424	Si-N	=2SC423: 0,2W	2a	Say	BFR36, BFW16..17, BFX55
2SC4240	Si-N	HF-L, 20V, 3A, 20W		Mit	—
2SC4241	Si-N	SMD, UHF, 20V, 0,08A, 6500MHz	44o	Nec	2SC4093
2SC4242	Si-N	S-L, 450/400V, 7A, 40W, 1/3µs	17j	Fjd	BUT56(A), 2SC3170, 2SC4055, 2SC4106, ++
2SC4243	Si-N	Vid, 300/300V, 0,1A, 1W, 100MHz	78b	Rhm	2SC2924, 2SC3408, 2SC3805, 2SC4019, ++
2SC4244	Si-N	SMD, UHF-V, 25V, 0,02A, 650MHz	35a(2mm)	Tos	BF517, BFS17, 2SC3161, 2SC4182..84, ++
2SC4245	Si-N	SMD, UHF-M, 30V, 0,05A, 2400MHz	35a(2mm)	Tos	BFT75, 2SC3014, 2SC3772..73, 2SC4083, ++
2SC4246	Si-N	SMD, UHF-O, 30V, 0,05A, 1500MHz	35a(2mm)	Tos	BFR53, 2SC3014, 2SC3016, 2SC4082, ++
2SC4247	Si-N	SMD, UHF-O, 20V, 0,03A, 4000MHz	35a(2mm)	Tos	BFQ29, BFQ61, BFR93, BFT75
2SC4248	Si-N	SMD, UHF-O, 20V, 0,03A, 4000MHz	35a(2mm)	Tos	BFQ29, BFQ81, BFR93, BFT75
2SC4249	Si-N	SMD, VHF-V, 30V, 0,02A, 650MHz	35a(2mm)	Tos	BF517, BFS17, 2SC3161, 2SC4183, ++
2SC425	Si-N	=2SC423: 20V	2a	Say	BFR36, BFW16..17, BFX55
2SC4250	Si-N	SMD, VHF-M, 30V, 0,05A, 1400MHz	35a(2mm)	Tos	BFR53, 2SC3014, 2SC3016, 2SC4082, ++
2SC4251	Si-N	SMD, VHF-O, 30V, 0,05A, 1100MHz	35a(2mm)	Tos	BFR53, 2SC3014, 2SC3016, 2SC4062, ++
2SC4252	Si-N	SMD, VHF-O, 20V, 0,03A, 2000MHz	35a(2mm)	Tos	BFR53, 2SC3014, 2SC3016, 2SC4062, ++
2SC4253	Si-N	SMD, TV-ZF-E, 30V, 0,05A, 600MHz	35a(2mm)	Tos	BF517, BFS17, 2SC3161, 2SC4082, ++
2SC4254	Si-N	SMD, Uni, 50V, 0,1A, 230MHz	35a(2mm)	Hit	BC646..847, 2SC4141, 2SC4177, ++
2SC4255	Si-N	SMD, TV-VHF, 20V, 0,03A, 2000MHz	35a	Tos	BF517, BFR53, 2SC3099, 2SC3773, ++
2SC4256	Si-N	Dynamic Focus, 1500/1200V, 0,01A, 5W	17j	Say	2SC4257, 2SC4451
2SC4257	Si-N	Dynamic Focus, 1500/1200V, 0,03A, 7W	17j	Say	2SC3675
2SC4258	Si-N	=2SC3053:	35a(2mm)	Mit	—
2SC4259	Si-N	=2SC4229:	35a(2mm)	Hit	—
2SC426	Si-N	=2SC423: 20V, 0,2W	2a	Say	BFR36, BFW16..17, BFX55
2SC4260	Si-N	=2SC4197:	35a(2mm)	Hit	—
2SC4261	Si-N	=2SC4196:	35a(2mm)	Hit	—
2SC4262	Si-N	=2SC3797:	35a(2mm)	Hit	BFT75, 2SC3772..73, 2SC3014, 2SC4245
2SC4263	Si-N	=2SC3493:	35a(2mm)	Hit	BF517, BFS17, 2SC3161, 2SC4062, ++
2SC4264	Si-N	=2SC2734:	35a(2mm)	Hit	BFT75, 2SC3014, 2SC3773, 2SC4260
2SC4265	Si-N	=2SC2735:	35a(2mm)	Hit	BFR53, 2SC3014, 2SC3016, 2SC4062, ++
2SC4266	Si-N	=2SC3926: 0,3W	41c	Mit	BC167, BC182, BC237, BC547, ++
2SC4267	Si-N	SMD, AM/FM, -/20V, 15mA, >450MHz	35a	Mat	BF564, BFS18..19, 2SC2404, 2SC2776, ++
2SC4269	Si-N	SMD, UHF, 30V, 0,05A, 1200MHz	35a	Say	BF517, BFS17, 2SC3016, 2SC3161, ++
2SC427	Si-N	Uni, 40V, 0,1A, 0,3W, 350MHz	2a	Say	BC167, BC182, BC237, BC547, 2N3904++
2SC4270	Si-N	SMD, UHF, 25V, 0,05A, 3000MHz	35a	Say	BFT75, 2SC3014, 2SC3161, 2SC3772..73
2SC4271	Si-N	Vid-E, hi-def, 30V, 0,3A, 5W, 2200MHz	14h	Say	—
2SC4272	Si-N	SMD, 27MHz-CB, 75V, 1A, PQ=1,6W(27MHz)	39b	Say	(BCX56, 2SD1005, 2SD1368, 2SD1422, ++)
2SC4273	Si-N	S-L, 500/400V, 5A, 40W, <1/3µs	17j	Fjd	BUT11(A), BUV46(A), 2SC2627, 2SC3497++
2SC4274	Si-N	S-L, 500/400V, 10A, 40W, <1/3µs	17j	Fjd	BUT12(A), BUT76(A), 2SC3562, 2SC4164
2SC4275	Si-N	S-L, 500/400V, 10A, 80W, <1/3µs	18j	Fjd	BUV47(A), BUW12(A), 2SC2828, 2SC3042++
2SC4276	Si-N	S-L, 500/400V, 15A, 80W, <1/3µs	18j	Fjd	BUV48(A..C), BUW13(A), 2SC3520, ++
2SC4277	Si-N	S-L, 500/400V, 5A, 60W, <1/3µs	16c	Rhm	(BUW11A, 2SC2962, 2SC3083, 2SC3153, ++)
2SC4278	Si-N	S-L, 150/150V, 10A, 100W, 20MHz	16c	Rhm	(BD245D, 2SC2637, 2SC2987A, 2SD1703++)
2SC428	Si-N	=2SC427: 20V	2a	Say	BC168, BC183, BC236, BC548, 2N3904++
2SC4283	Si-N	S-L, 1200/800V, 3A, 50W, <0,5/3,8µs	16c	Sak	2SC4583
2SC4284	Si-N	S-L, 1400/600V, 6A, 150W, <1/4,3µs	23a	Tos	MJ6505, 2SC3594
2SC4285	Si-N	S-L, 1400/600V, 10A, 150W, <1/4,3µs	23a	Tos	BUX86, MJ8505
2SC4286	Si-N	=2SC4284: 100W	77c	Tos	—
2SC4287	Si-N	=2SC4265: 100W	77c	Tos	—
2SC4288	Si-N	S-L, HA, hi-res, 1400/600V, 12A, 200W	77j	Tos	2SC3995
2SC4288A	Si-N	=2SC4288: 1500/600V	77j		2SC3995
2SC4289	Si-N	S-L, HA, hi-res, 1400/600V, 16A, 200W	77j	Tos	2SC3998
2SC4289A	Si-N	=2SC4286: 1500/800V	77j		2SC3998
2SC429	Si-N	Min, FM, 25V, 0,01A, 380MHz	24b	Nec	(BF196..199, BF224..225, BF314, ++)
2SC4290	Si-N	S-L, HA, hi-res, 1400/600V, 20A, 200W	77j	Tos	2SC3997
2SCA76554290A	Si-N	=2SC4286: 1500/600V	77j		2SC3997
2SC4291	Si-N+Di	HA, hi-def, 1500/800V, 5A, 100W	18j	Say	2SC3481..82, 2SC3681, (BU506D, 2SD1730)
2SC4292	Si-N+Di	HA, hi-def, 1500/800V, 6A, 100W	16j	Say	2SC3462, 2SC3681, (BU508D, 2SD1731)
2SC4293	Si-N+Di	=2SC4291: Iso, 50W	16c	Say	2SC3892A, 2SC4122, (BU508DF, 2SD1731)
2SC4294	Si-N+Di	=2SC4292: Iso, 50W	16c	Say	2SC3892A, 2SC4122, (BU508DF, 2SD1731)
2SC4295(M)	Si-N	S, 400/400V, 0,1A, 1W, 1/7,2µs	9c	Rhm	BF467, MPS-A45, 2SC3469, 2SD1365, ++
2SC4298	Si-N	S-Reg, 500/400V, 10A, 75W, <1/3,5µs	16c	Sak	2SC4423, (BUV47(A..C), BUW12(A), ++)
2SC4297	Si-N	S-Reg, 500/400V, 12A, 75W, <1/3,5µs	16c	Sak	2SC4423, (BUV47(A..C), BUW13(A), ++)

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2SC4298	Si-N	S-Reg, 500/400V, 15A, 80W, <1/3,5µs	18c	Sak	2SC4424, (BUV47(A..C), BUW13(A),++)
2SC4299	Si-N	S-Reg, 900/800V, 3A, 70W, <1/6µs	18c	Sak	2SC4426, (BUW11A, 2SC3152..53, 2SC3550)
2SC42A	Si-N	=2SC41: 200V	23a		BD245F, 2SC2262, 2SD555, 2SD751, ++
2SC43	Si-N	=2SC41: 100V, B>4	23a	Son	BD245C, BDV95, BDX95, 2N5758, ++
2SC430	Si-N	=2SC429: 420MHz	24b	Nec	(BF198..199, BF224..225, BF314,++)
2SC4300	Si-N	S-Reg, 900/800V, 5A, 75W, <1/6µs	18c	Sak	2SC4426, (BUW11A, 2SC3232, 2SC3636,++)
2SC4301	Si-N	S-Reg, 900/800V, 7A, 60W, <1/6µs	18c	Sak	2SC4429, (BUV69, 2SC3466, 2SC3636)
2SC4302	Si-N	S-Reg, 900/800V, 5A, 75W, <1/4,5µs	18c	Sak	2SC4426, (BUW11A, 2SC3232, 2SC3636,++)
2SC4303	Si-N	S-L, 1400/800V, 6A, 60W, <1/4,3µs	18c	Sak	BU508AF, 2SC4941, 2SD1547, 2SD2252, ++
2SC4303A	Si-N	=2SC4303: 1500/800V	18c		BU508AF, 2SC3695, 2SD1747, 2SD2252, ++
2SC4304	Si-N	S-Reg, 900/800V, 3A, 35W, <0,7/4,7µs	17c	Sak	BUT11AF, 2SC3559, 2SC4234, 2SD1581, ++
2SC4305	Si-N	S-L, 100/40V, 7A, 40W, <1/3,5µs	15j	Nec	BD543C, BD711, BD601, MJE15026, ++
2SC4306	Si-N	S-L, Io-sat, 30V, 8A, 15W, <300/1150ns	30j	Say	2SC4666, 2SD1804
2SC4306	Si-N	VHF-A, 30V, 0,3A, 0,6W, 2500MHz	7f	Hit	2SC4693
2SC4309	Si-N	S-L, 1000/600V, 6A, 150W, <500/2130ns	17j	Mat	2SC3736, 2SC3982A, 2SC3992
2SC431	Si-N	S-L, 150/100V, 30A, 200W, B>10	66a	Shi	2SC1299, 2SC1301, 2SC1672, 2SC2126, ++
2SC4310	Si-N	S-L, 900/800V, 6A, 50W, <500/3500ns	17j	Shi	BUT11(A), BUT16(A), BUT58(A), ++
2SC4311	Si-N	=2SC4310: Iso, 40W	15c	Shi	BUT11(A)F, BUT16(A)F, BUV46(A)FI, ++
2SC4312	Si-N	S-L, 900/800V, 6A, 80W, <500/3500ns	16j	Shi	BUW11A, BUW131A, 2SC3535..36,++
2SC4313	Si-N	S-L, 900/800V, 10A, 100W, <500/3500ns	16j	Shi	BUV47A, BUW12A, 2SC3637..36
2SC4314	Si-N	S-L, 900/800V, 15A, 130W, <500/3500ns	16j	Shi	BUV48A, BUW13A, BUW133A, 2SC3636
2SC4315	Si-N	SMD, VHF/UHF, ra, 20V, 0,08A, 7GHz	44u	Tos	—
2SC4316	Si-N	VHF/UHF, ra, 20V, 40mA, 9000MHz	7l	Tos	—
2SC4317	Si-N	=2SC4316 SMD, 10GHz	35a	Tos	2SC5089
2SC4316	Si-N	=2SC4316: SMD	39b	Tos	—
2SC4319	Si-N	=2SC4316: 10GHz	25q	Tos	—
2SC432	Si-N	=2SC431: B>20	68a	Shi	2SC1299, 2SC1301, 2SC1672, 2SC2126, ++
2SC4320	Si-N	=2SC4316: SMD, 10GHz	44u	Tos	2SC5092
2SC4321	Si-N	=2SC4316: SMD, 10GHz	35a(2mm)	Tos	2SC5090
2SC4322	Si-N	SMD, VHF/UHF, ra, 10V, 25mA, 10GHz	35a	Tos	BFR505, 2SC5094
2SC4323	Si-N	=2SC4322:	25q	Tos	(2SC3566..67)
2SC4324	Si-N	=2SC4322:	44u	Tos	—
2SC4325	Si-N	=2SC4322:	35a(2mm)	Tos	(2SC3585)
2SC4326(LK)	Si-N	SMD, UHF, 12V, 0,05A, 800MHz	35a	Rhm	BF517, BFS17, 2SC3016, 2SC3161, ++
2SC4327	Si-N	Motor-Tr, Io-sat, 50V, 7A, 25W, 115MHz	17c	Sak	2SC3747..46, 2SC4550
2SC4326	Si-N	S-L, Io-sat, 150V, 5A, 30W, <300/1900ns	17j	Nec	—
2SC4329	Si-N	S-L, Io-sat, 150V, 7A, 35W, <300/1900ns	17j	Nec	—
2SC433	Si-N	=2SC431: 200/140V	66a	Shi	2SC1299, 2SC1301, 2SC1673, 2SC2128, ++
2SC4330	Si-N	S-L, 150V, 10A, 40W, <300/1900ns	17j	Nec	—
2SC4331(Z)	Si-N	Io-sat, 150/100V, 5A, 15W, 150MHz	30j	Nec	2SC4343
2SC4332(Z)	Si-N	S-L, 100V, 5A, 15W, <300/1800ns	30j	Nec	2SC3303, 2SC4344
2SC4333(Z)	Si-N	S-L, 40V, 7A, 15W, <300/1800ns	30j	Nec	2SD1804
2SC4334	Si-N	=2SC4326: Iso, 25W	17c	Nec	2SC3566, 2SC3696
2SC4335	Si-N	=2SC4329: Iso, 30W	17c	Nec	2SC3566, 2SC3697, 2SD1792
2SC4336	Si-N	=2SC4330: Iso, 30W	17c	Nec	2SC3568, 2SC3696, 2SD1794
2SC4337(Z)	Si-N-Darl+Di	S-L, 60V, ±1A, 7W, B=10000	30j	Nec	2SC2671, 2SD1596, 2SD1800
2SC4336(Z)	Si-N-Darl+Di	S-L, 80V, ±2A, 6W, B=10000	30j	Nec	2SD1617, 2SD1980
2SC4339(Z)	Si-N-Darl+Di	S-L, 150/100V, ±3A, 9W, B=10000	30j	Nec	—
2SC434(A)	Si-N	=2SC431: 200/140(A=200/200)V, B>20	68a	Shi	2SC1299, 2SC1301, 2SC1673, 2SC2126, ++
2SC4340	Si-N-Darl+Di	=2SC4337: 8W	14h	Nec	BD675, BD677, BD679, BDX42..44
2SC4341	Si-N-Darl+Di	=2SC4338: 10W	14h	Nec	(BD679, BD661, BD663, BD779, 2N6039)
2SC4342	Si-N-Darl+Di	=2SC4339: 12W	14h	Nec	—
2SC4343(Z)	Si-N	S-L, 150V, 7A, 16W, <300/1900ns	30j	Nec	—
2SC4344(Z)	Si-N	S-L, 100V, 7A, 16W, <300/1800ns	30j	Nec	2SC4979
2SC4345(Z)	Si-N-Darl	S-L, 100V, 5A, 12W, B=10000	30j	Nec	—
2SC4346(Z)	Si-N	S-L, 500/400V, 5A, 18W, <700/2800ns	30j	Nec	(BUT11(A), BUV46(A), 2SC3497,++)
2SC4347	Si-N-Darl+Di	Z-Di(B→C), ±60V, 5A, 25W, B=10000	15j	Nec	—
2SC4346	Si-N-Darl+Di	S-L, 100V, ±5A, 25W, B=10000	15j	Nec	—
2SC4349	Si-N-Darl+Di	S-L, 100V, 8A, 30W, B=10000	15j	Nec	—
2SC435	Si-N	=2SC431: 300/200V	66a	Shi	2SC1299, 2SC1302, 2SC1401, 2SC1673, ++
2SC4350	Si-N-Darl+Di	S-L, 100V, 10A, 40W, B=10000	15j	Nec	—
2SC4351	Si-N-Darl+Di	=2SC4347: Iso, 20W	17c	Nec	—
2SC4352	Si-N-Darl+Di	=2SC4348: Iso, 20W	17c	Nec	—
2SC4353	Si-N-Darl+Di	=2SC4350: Iso, 25W	17c	Nec	—
2SC4354	Si-N	S-L, 400/400V, 2A, 15W, <1/3,5µs	78c	Rhm	(BUX84..85, 2SC2736, 2SC3169,++)
2SC4355	Si-N	S-L, 100V, 4A, 10MHz	78c	Rhm	—

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2SC4356	Si-N	Uni, 60V, 2A, 0,9W, 80MHz	7c(9mm)	Mit	2SC3328, 2SD1014, 2SD1207, 2SD1146, ++
2SC4357	Si-N	=2SC4356: SMD	39b	Mit	2SC3647, 2SC4132, 2SD1623, 2SD1422
2SC4358	Si-N	35V, 0,3A, 2500MHz	17c	Mat	—
2SC4359	Si-N	S-L, 900/800V, 3A, 70W, <700/2800ns	16c	Mat	BUW11AF, 2SC4299, 2SC4445
2SC436	Si-N	=2SC431: 300/200V, B>20	68a	Shi	2SC1299, 2SC1302, 2SC1401, 2SC1873, ++
2SC4360	Si-N+R	=2SC4361: SMD	35a	Say	FA113N, DTC143XK, KSR1105, UN221F
2SC4361	Si-N+R	S, 50V, 0,1A, 0,3W, Rb=4,7k, Rbe=10kΩ	40c	Say	AA113N, DTC143XS, KSR1005, UN421F
2SC4362	Si-N+R	=2SC4363: SMD	35a	Say	FA113M, DTC143EK, RN1401, UN221L++
2SC4363	Si-N+R	S, 50V, 0,1A, 0,3W, Rb=Rbe=4,7kΩ	40c	Say	AA113M, DTC143ES, RN1001, UN421L++
2SC4364	Si-N	SMD, UHF, 25V, 0,03A, 3000MHz	35a	Say	BF775, BFR35, 2SC3014, 2SC3098
2SC4365	Si-N	SMD, UHF, 25V, 0,05A, 3000MHz	35a	Say	BFT75, 2SC3014, 2SC3772 3773
2SC4366	Si-N	=2SC3836: SMD, 250MHz	35a	Hit	—
2SC4367	Si-N	HF, 30V, 0,1A, 0,6W, 1000MHz	7c(9mm)	Hit	—
2SC4368	Si-N	NF/S-L, 150V, 1,5A, 20W, 4MHz	17c	Kec	2SC3298(A,B), 2SC3567, 2SC3695, 2SC4159
2SC4369	Si-N	NF/S-L, 30V, 3A, 15W, 100MHz	17c	Kec	2SC3297, 2SC3690
2SC437	Si-N	HF/S-L, 100V, 2A, 13W, 210MHz	2a	Mit	(BD379, BD529, 2SD1177..1178, ++)
2SC4370	Si-N	NF/S-L, 160V, 1,5A, 20W, 100MHz	17c	Kec	2SC3298(A,B), 2SC3364, 2SC4159
2SC4371	Si-N	S-L, 500/400V, 5A, 30W, <1/3,5µs	17c	Kec	BUT11(A)F, 2SC3570, 2SC3573, 2SC4073, ++
2SC4372A7817	Si-N	SMD, Uni, 200V, 0,05A, 120MHz	39b	Kec	BF620, BF622, 2SC2860, 2SC3360, ++
2SC4373	Si-N	SMD, Uni, 120V, 0,8A, 120MHz	39b	Kec	BCX41, 2SC2881, 2SD1007, 2SD1418..19
2SC4374	Si-N	SMD, Uni, 80V, 0,4A, 100MHz	39b	Kec	BCW68, 2SC2882, 2SC3438, 2SD875, ++
2SC4375	Si-N	SMD, Uni, 30V, 1,5A, 120MHz	39b	Kec	2SC2982, 2SC3439, 2SD1766
2SC4376	Si-N	SMD, Uni, 35V, 0,8A, 120MHz	39b	Kec	BCX54..56, 2SC2884, 2SC3444, 2SD874A
2SC4377	Si-N	SMD, Uni, 30V, 2A, 150MHz	39b	Kec	2SD1119, 2SD1620, 2SD1768
2SC4378	Si-N	Vid-L, 300V, 0,2A, 10W, 70MHz	14b	Say	(BF417, BF817, BF758..759, ++)
2SC4379	Si-N	S-L, 500/400V, 15A, 120W, <500/2100ns	16c	Mat	2SC4424, (BUV48(AC), BUW13(A), ++)
2SC436	Si-N	=2SC437: 75V	2a	Mit	(BD377, BD527, 2SD1177..1178, ++)
2SC4381	Si-N	TV-NF-L, 150/150V, 2A, 25W, 15MHz	17c	Sak	BDT31DF, 2SC3298(A..B), 2SC3587, ++
2SC4382	Si-N	=2SC4361: 200/200V	17c	Sak	2SC3298B, 2SD1587
2SC4383	Si-N	S-L, 200/160V, 8A, 40W, <2/5µs	16c	Fjd	(BD245F, 2SC2789, 2SC3855, 2SD751, ++)
2SC4385	Si-N	NF/S-L, 120/80V, 8A, 60W, 20MHz	16c	Sak	(BD245C..F, 2SC3181, 2SD718, 2SD898, ++)
2SC4366	Si-N	NF/S-L, 160/120V, 8A, 75W, 20MHz	16c	Sak	(BD245D..F, 2SC2837, 2SD1046)
2SC4387	Si-N	NF/S-L, 200/140V, 10A, 80W, 20MHz	16c	Sak	(2SC2581, 2SC3263, 2SC3855)
2SC4388	Si-N	NF/S-L, 200/160V, 15A, 85W, 20MHz	16c	Sak	(2SC3263, 2SC3656)
2SC4389	Si-N	hi-Ueb, hi-beta, lo-sat, 30V, 2A, B>800	7c(9mm)	Say	2SD1581, 2SD1779, (2SC3225)
2SC439	Si-N	HF, 25V, 0,1A, 0,5W, 420MHz	2a	Mit	BFX55, 2N3299..3300, 2N3724, 2SC1365, ++
2SC4390	Si-N	SMD, hi-Ueb, hi-beta, lo-sat, 20V, 2A, B>800	39b	Say	2SD1950
2SC4391	Si-N	NF, 60V, 1A, 1W, 120MHz	9c	Mat	BC639, MRS851, 2SC3669, 2SD819, ++)
2SC4392	Si-N	SMD, UHF, 20V, 30mA, 6500MHz	35a(2mm)	Tos	(2SC3011)
2SC4393	Si-N	SMD, VHF/UHF, 17V, 70mA, 5000MHz	35a(2mm)	Tos	(2SC3161, 2SC3774)
2SC4394	Si-N	SMD, VHF/UHF, 20V, 60mA, 7000MHz	35a(2mm)	Tos	(2SC3445)
2SC4398	Si-N+R	SMD, S, 50V, 0,1A, 250MHz, Rb=Rbe=47kΩ	35a(2mm)	Say	—
2SC4397	Si-N+R	SMD, S, 50V, 0,1A, 250MHz, Rb=Rbe=22kΩ	35a(2mm)	Say	—
2SC4398	Si-N+R	SMD, S, 50V, 0,1A, 250MHz, Rb=Rbe=10kΩ	35a(2mm)	Say	—
2SC4399	Si-N	SMD, HF, 20V, 30mA, 320MHz	35a(2mm)	Say	—
2SC44	Si-N	=2SC41: 50V, B>4	23a	Son	BD245, BDV91, BDX91, 2N4914, ++
2SC440	Si-N	HF, 25V, 0,1A, 0,5W, 420MHz	2a	Mit	BFX55, 2N3299..3300, 2N3724, 2SC1365, ++
2SC4400	Si-N	SMD, FM/VHF, 40V, 50mA, 750MHz	35a(2mm)	Say	—
2SC4401	Si-N	SMD, UHF, 25V, 30mA, 3000MHz	35a(2mm)	Say	(BF775, 2SC3098)
2SC4402	Si-N	SMD, UHF, 25V, 50mA, 3000MHz	35a(2mm)	Say	(2SC3014, 2SC3773)
2SC4403	Si-N	SMD, UHF, 25V, 70mA, 3000MHz	35a(2mm)	Say	(2SC3772)
2SC4404	Si-N	SMD, UHF, 20V, 70mA, 5000MHz	35a(2mm)	Say	(2SC3161, 2SC3774)
2SC4405	Si-N	SMD, UHF, 20V, 100mA, 5000MHz	35a(2mm)	Say	(2SC3775)
2SC4406	Si-N	SMD, UHF, 30V, 50mA, 1200MHz	35a(2mm)	Say	(BFR53, 2SC3014, 2SC3773)
2SC4407	Si-N	SMD, UHF, 25V, 50mA, 3000MHz	35a(2mm)	Say	(2SC3014, 2SC3773)
2SC4406	Si-N	S, lo-sat, 60V, 2A, 0,9W, 100/600ns	7c(9mm)	Tos	2SC3328
2SC4409	Si-N	=2SC4406: SMD	39b	Tos	2SC4541
2SC441	Si-N	HF, 25V, 0,1A, 0,5W, 420MHz	2a	Mit	BFX55, 2N3299..3300, 2N3724, 2SC1365, ++
2SC4410	Si-N	=2SC3707:	35a(2mm)	Mat	—
2SC4411	Si-N	Vid-E, hi-def, 100V, 0,5A, 15W, 1200MHz	17j	Say	2SC4201..4202
2SC4412	Si-N	SMD, CTV-Vid, 300V, 0,05A, 70MHz	35a	Say	BF820, 2SC4062
2SC4413	Si-N	SMD, hi-Ueb, hi-beta, 60V, 0,1A, B>800	35a(2mm)	Say	—
2SC4414	Si-N	lo-sat, 100V, 0,5A, 0,3W, 120MHz, 50/740ns	40c	Say	—
2SC4415	Si-N	=2SC4229:	44o	Hit	—
2SC4416	Si-N	=2SC4197:	35d	Hit	—
2SC4417	Si-N	=2SC4444:	35a(2mm)	Mat	—

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2SC4418	Si-N	S-Reg, 500/400V, 5A, 30W, 20MHz	17c	Sak	2SC3573, 2SC4054, 2SC4073, 2SC4371, ++
2SC4419	Si-N	S-L, 900/800V, 6A, 100W, <1µ/4,8µs	18j	F|d	BUW11A, BUW132A, 2SC3536, 2SC3636, ++
2SC442	Si-N	HF, 50V, 0,1A, 0,5W, 420MHz	2a	Mit	BFX55, 2N3299 3300, 2N3724, 2SC1385, ++
2SC4420	Si-N	S-L, 900/800V, 3A, 70W, <700/2800ns	16c	Mat	(BUW11A, 2SC3152, 2SC3376, 2SC3550, ++)
2SC4421	Si-N	S-L, 500/400V, 3A, 40W, <500/2100ns	17c	Mat	BUT 11(A)F, 2SC3570, 2SC4052, 2SC4160, ++
2SC4422	Si-N	=2SC3513: 0,4W	39b	Hit	2SC3807
2SC4423	Si-N	S-L, 500/400V, 12A, 55W, 20MHz	16c	Say	2SC4297, (BUW13(A), BUV48(A..C, ++)
2SC4424	Si-N	S-L, 500/400V, 16A, 60W, 20MHz	16c	Say	2SC4298, (BUW13(A), BUV48(A..C, ++)
2SC4425	Si-N	S-L, 500/400V, 25A, 65W, 20MHz	18c	Say	2SC4461, (2SC3850, 2SC4110)
2SC4426	Si-N	S-L, 1100/800V, 3A, 45W, 15MHz	18c	Say	2SC4583, (2SC3387, 2SC3480, 2SC3642)
2SC4427	Si-N	S-L, 1100/800V, 4,5A, 50W, 15MHz	18c	Say	2SC4584, (2SC3387, 2SC3460, 2SC3642)
2SC4428	Si-N	S-L, 1100/800V, 6A, 55W, 15MHz	16c	Say	2SC4584, (BUV89, 2SC3466, 2SC3643)
2SC4429	Si-N	S-L, 1100/800V, 8A, 60W, 15MHz	16c	Say	2SC4199, 2SC4585, (BUV89, 2SC3843, ++)
2SC443	Si-N	FM-Tr, 50V, 0,5A, 0,8W, 200MHz	2a	Mit	BFS23, BFX55, BLY34
2SC4430	Si-N	S-L, 1100/800V, 12A, 65W, 15MHz	16c	Say	2SC4585, (BUV48B,C, 2SC3552, 2SC3644)
2SC4431	Si-N	NF/HF-L, 120/120V, 1,5A, 20W, 150MHz	17c	Nec	2SC3298(A,B), 2SC3564, 2SC4370, 2SD1763+
2SC4432	Si-N	SMD, FM/VHF, 40V, 0,05A, 750MHz	35a	Say	BF599, BF799, BFS20, 2SC3374, ++
2SC4433	Si-N	FM, 40V, 50mA, 0,3W, 750MHz	40c	Say	BF314, BF502, BF505, BF507, BF562++
2SC4434	Si-N	S-L, 500/400V, 15A, 120W, <500/2150ns	18j	Sak	BUV48(A..C), 2SC4139, 2SC4140, ++
2SC4435	Si-N	HA, hi-def, 1500/800V, 5A, 100W	18j	Say	2SC3485..66, 2SC3685, (BU508A, ++)
2SC4436	Si-N	HA, hi-def, 1500/800V, 6A, 100W	18j	Say	2SC3466, 2SC3685..66, (BU508A, ++)
2SC4437	Si-N	=2SC4435: Iso, 50W	16c	Say	2SC3894, (BU508AR, 2SD1855..56, ++)
2SC4438	Si-N	=2SC4435: Iso, 50W	18c	Say	2SC3894, (BU508AF, 2SC4143, 2SD1656, ++)
2SC4439	Si-N	Vid-E, hi-res, 160V, 0,3A, 8W, 400MHz	14b	Tos	S3936, 2SC4564, 2SC4623
2SC444	Si-N	FM-Tr, 60V, 0,5A, 0,8W, 220MHz	2a	Mit	BFS23, BFX55, BLY34
2SC4440	Si-N	HA, monochrome, 600/400V, 7A, 30W	17c	Say	BU307F
2SC4441	Si-N	HA, monochrome, 600/400V, 10A, 35W	17c	Say	—
2SC4442	Si-N	S-L, 500/400V, 4A, 45W, <500/2100ns	17c	Mat	2SC4054, 2SC4073, 2SC4160, 2SC4371, ++
2SC4443	Si-N	SMD, S, 20V, 0,15A, 700MHz	35a(2mm)	Say	(2SC4168)
2SC4444	Si-N	SMD, VHF/ZF, 45V, 0,05A, 500MHz	35a	Mat	BF517, BFS17, 2SC3016, 2SC3161
2SC4445	Si-N	S-L, 900/800V, 3A, 60W, <700/4700ns	16c	Sak	BUW11AF, 2SC4299, 2SC4300, 2SC4426
2SC4446	Si-N	SMD, hi-Ueb, 60V, 0,15A, 130MHz	35a(2mm)	Say	(2SC4116)
2SC4448	Si-N	Vid-E, hi-res, 250V, 0,15A, 10W, 240MHz	17c	Tos	S3540
2SC4449	Si-N	Vid, 300/300V, 0,05A, 0,6W, 70MHz	7c	Say	BF299, BF420(A), 2SC3468
2SC445	Si-N	FM-Tr, 60V, 0,5A, 0,8W, 220MHz	2a	Mit	(BFS23, BFX55, BLY34)
2SC4450	Si-N	DynamicFocus, 1500/1500V, 5mA, 6MHz	17j	Say	2SC4256
2SC4451	Si-N	DynamicFocus, 1500/1500V, 15mA, 6MHz	17j	Say	2SC4257
2SC4452	Si-N	=2SC4455: SMD	35a(2mm)	Say	2SC4175..78
2SC4453	Si-N	=2SC4455: SMD	35a(3mm)	Say	2SC3735
2SC4454	Si-N	=2SC4455: 0,3W	40c	Say	→2SC4455
2SC4455	Si-N	SS, 40V, 0,2A, 0,6W, 750MHz, <12/18ns	7e	Say	BSS11, 2N2368..69(A), 2SC2901
2SC4457	Si-N	S-Reg, 800/500V, 4A, 40W, <500/3300ns	16c	Say	BUW11(A)F, 2SC4300, 2SC4586
2SC4456	Si-N	S-Reg, 600/500V, 7A, 45W, <500/3300ns	16c	Say	BUV47(A)FI, BUW12(A)F, 2SC4301
2SC4459	Si-N	S-Reg, 600/500V, 10A, 50W, <500/3300ns	18c	Say	BUP23CF, BUV46(A)FI, BUW13(A)F
2SC446	Si-N	FM-Tr, 60V, 0,5A, 0,8W, 220MHz	2a	Mit	BFS23, BFX55, BLY34
2SC4460	Si-N	S-Reg, 800/500V, 15A, 55W, <500/3300ns	18c	Say	BUP23CF, BUV46(A)FI, BUW13(A)F
2SC4461	Si-N	S-Reg, 600/500V, 25A, 65W, <500/3300ns	18c	Say	BUX98(A)PI
2SC4462	Si-N	=2SC2732:	35a(2mm)	Hit	—
2SC4463	Si-N	=2SC2733:	35a(2mm)	Hit	—
2SC4464	Si-N	SMD, UHF, 15V, 5mA, 4000MHz	35a(2mm)	Hit	—
2SC4466	Si-N	NF-L, 120/80V, 8A, 60W, 20MHz	18j	Sak	BD245C..F, 2SC2681, 2SC3181, 2SB898, ++
2SC4467	Si-N	NF-L, 160/120V, 8A, 80W, 20MHz	18j	Sak	BD245D..F, 2SC2837, 2SC2987, 2SD1047(A)
2SC4466	Si-N	NF-L, lo-sat, 200/140V, 10A, 80W, 20MHz	18j	Sak	(BD245F, 2SC3855, 2SC3283, 2SC3856)
2SC447	Si-N	HF-L, 75V, 2A, 25W, 210MHz	49a	Mit	(BLY35, 2N3632)
2SC4470	Si-N	VHF..UHF, 20V, 0,08A, 7GHz	35d	Tos	—
2SC4471	Si-N	S-L, 600/500V, 4A, 50W, <500/2100ns	17c	Mat	BUT11(A)F, BUT21CF, 2SC3750, 2SC3795
2SC4471A	Si-N	=2SC4471: 900/500V	17c		BUT11AF, 2SC3895A, 2SC4518(A)
2SC4473	Si-N	Vid-L, 120/120V, 0,4A, 10W, 400MHz	17c	Say	(2SC3781)
2SC4474	Si-N	Vid-L, 200/200V, 0,2A, 10W, 300MHz	17c	Say	2SC3565
2SC4475	Si-N	TV, Dynamic Fokus, 2000/1800V, 3mA	17j	Say	—
2SC4476	Si-N	TV, Dynamic Fokus, 2000/1800V, 10mA	17j	Say	—
2SC4477	Si-N	AMP, 330/150V, 7A, 30W, tf<300ns	17c	Say	BU406F..407F, 2SD1404, (2SC3590..91)
2SC4478	Si-N	=2SC4477: 400/200V	17c	Say	BU406F, (2SC3175, 2SC3591)
2SC4479	Si-N	Vid-E, hi-res, 100V, 0,5A, 10W, 1100MHz	14b	Tos	2SC4563
2SC448	Si-N	HF-L, 100V, 2A, 25W, 190MHz	49a	Mit	—
2SC4460	Si-N	=2SC4389: Fig. →	9c	Say	(2SC3225, 2SC4389, 2SD1246..47)

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2SC4481	Si-N	S, 15V, 1,5A, 0,9W, 200MHz	9c	Say	—
2SC4482	Si-N	S, Io-sat, 60V, 5A, 1W, 150MHz	9c	Say	2SD1145
2SC4483	Si-N	NF, Io-sat, 30V, 1,5A, 1W, 150MHz	9c	Say	2SD1207, 2SD1246..47, 2SD2177
2SC4484	Si-N	NF, S, Io-sat, 30V, 2,5A, 1W, 150MHz	9c	Say	2SD879, 2SD1207, 2SD1347
2SC4485	Si-N	NF, S, Io-sat, 60V, 1A, 0,9W, 150MHz	9c	Say	2SD1207, 2SD1582, 2SD1835
2SC4486	Si-N	NF, S, Io-sat, 60V, 2A, 1W, 150MHz	9c	Say	2SD1207, 2SD1835
2SC4487	Si-N	NF, S, Io-sat, 60V, 3A, 1W, 150MHz	9c	Say	2SD1347
2SC4488	Si-N	NF, S, Io-sat, 120V, 1A, 1W, 120MHz	9c	Say	—
2SC4489	Si-N	NF, S, Io-sat, 120V, 2A, 1W, 120MHz	9c	Say	—
2SC449	Si-N	HF-L, 75V, 2A, 25W, 190MHz	49a	Mit	(BLY35, 2N3632)
2SC4490	Si-N	CRT, hi-def, 300/300V, 0,1A, 1W, 70MHz	9c	Say	2SC3488
2SC4491	Si-N-Darl+Di	+Z-Di(B→C)50V, 1,2A, 1W, B>1000	9c	Say	—
2SC4492	Si-N	S-L, 600/600V, 0,02A, 40MHz	30c	Say	(2SC4257, 2SC4572)
2SC4493	Si-N	S-L, 800/800V, 0,02A, 40MHz	30c	Say	(2SC4257, 2SC4572)
2SC4494	Si-N	Io-sat, 60V, 3A, 25W, 40MHz, hi-B>500	17c	Sak	2SC3852, 2SD2127, 2SD2092, 2SD1948
2SC4495	Si-N	=2SC4494: 80V	17c	Sak	2SC3852, 2SD1944, 2SD2076
2SC4496	Si-N-Darl+Di	Z-i, 90V, ±8A, 30W, 400/3000ns, B>2000	17j	Nec	2SD2024
2SC4497	Si-N	SMD, Nix, Video, 300V, 0,1A, 70MHz	35a	Tos	BFN26, 2SC4061
2SC4498	Si-N+R	SMD, S, 50V, 0,1A, Rb=2,2kΩ, Rbe=10kΩ	35a(2mm)	Say	—
2SC4499L,S	Si-N	S-L, 500/400V, 0,5A, 10W, <1/3µs	30j	Hit	2SC3075, 2SC3129, 2SC3588
2SC45	Si-N	HF, 45V, 0,1A, 0,5W, 160MHz	2a	Nec	BFW16..17, BFX55
2SC450	Si-N	HF-L, 60V, 2A, 25W, 210MHz	49a	Mit	(BLY35, 2N3632)
2SC4500L,S	Si-N-Darl	S-L, 60V, 1A, 8W, B>2000, 100/600ns	30j	Hit	2SC2871, 2SD1598, 2SD1800
2SC4501L,S	Si-N-Darl	S-L, 30V, 3A, 10W, B>2000, 400/1200ns	30j	Hit	2SC3132, 2SD1222, 2SD1799
2SC4502	Si-N	ZF, 50V, 0,05A, 1W, 500MHz	9c	Mat	BF370, BF921, BF959
2SC4503	Si-N	hi-Ueb, Io-sat, 100V, 30A, 80W, 20MHz	18c	Sak	—
2SC4504	Si-N	SMD, Vid, hi-res, 30V, 0,3A, 3GHz	39b	Say	—
2SC4505	Si-N	SMD, S, 400/400V, 0,1A, 20MHz	39b	Rhm	2SC4548
2SC4506	Si-N	Vid, 300/300V, 0,1A, 1,5W, 100MHz	78c	Rhm	(BF417, BF459, 2SC3503, 2SC4147++)
2SC4507	Si-N	S-L, 500/400V, 5A, 40W, <1/3µs	17c	Fjd	BUT11(A)F, 2SC4026, 2SC4073, 2SC4418, ++
2SC4508	Si-N	S-L, 500/400V, 10A, 40W, <1/3µs	17c	Fjd	BUT12(A)F, 2SC3871, 2SC4162, 2SD1795, ++
2SC4509(R)	Si-N	S-L, 500/400V, 10A, 80W, <1/3µs	18c	Fjd	BUW13(A)F, 2SC4296..97, 2SC4423, ++
2SC451	Si-N	HF-L, 100V, 1,2A, 25W, 180MHz	49a	Mit	—
2SC4510(R)	Si-N	S-L, 500/400V, 15A, 60W, <1/3µs	18c	Fjd	BUV46(A)F, BUW13(A)F, 2SC4296, 2SC4424
2SC4511	Si-N	=2SC4512: Iso, 30W	17c	Sak	BDT41BF..CF, 2SC4335
2SC4512	Si-N	NF/S-L, 120/60V, 6A, 50W, 20MHz	17j	Sak	BD243C..F, BD543D, 2SC4329, 2SD866
2SC4515	Si-N	UHF, 15V, 0,05A, 0,2W, 7GHz	44u	Mat	—
2SC4516	Si-N	UHF, 15V, 0,08A, 0,2W, 8GHz	44u	Mat	—
2SC4517	Si-N	S-Reg, 900/550V, 3A, 30W, <700/4500µs	17c	Sak	BUT11AF, 2SC4304, 2SC3559, 2SC3979A, ++
2SC4517A	Si-N	=2SC4517: 1000/550	17c		BUT11AF, 2SC3752, 2SC3979A
2SC4518	Si-N	S-Reg, 900/550V, 5A, 35W, <700/4500µs	17c	Sak	BUT11AF, BUT19AF, 2SC3795A
2SC4518A	Si-N	=2SC4518: 1000/550V	17c		BUT11AF, BUT18AF
2SC4519	Si-N	SMD, S, Io-sat, 60V, 0,5A, <120/350ns	35a	Say	—
2SC452	Si-N	HF-L, 100V, 1,2A, 25W, 160MHz	49a	Mit	—
2SC4520	Si-N	SMD, S, 60V, 1,5A, 50/180ns	39b	Say	—
2SC4521	Si-N	SMD, S, 60V, 3A, 50/180ns	39b	Say	—
2SC4522	Si-N	S-L, 60V, 5A, 15W, 50/180ns	30j	Say	2SC3074, 2SD1803
2SC4523	Si-N	S-L, 60V, 8A, 15W, 50/180ns	30j	Say	2SD1804
2SC4524	Si-N	UHF-L, 50V, 2,5A, PO>7W(1650MHz)		Mit	—
2SC4525	Si-N	UHF-L, 50V, 5A, PO>20W(1650MHz)		Mit	—
2SC4526	Si-N	UHF-L, 50V, 7,5A, PO>28W(1650MHz)		Mit	—
2SC4527	Si-N	SMD, TV-UHF-Tuner, 30V, 0,05A, 1500MHz	35d	Tos	—
2SC4528	Si-N-Darl+Di	int Diode(E→B), 1500/500V, 10A, 150W	81c(G)	Mat	—
2SC4529	Si-N	A, VHF-L, 30V, 0,3A, 5W, >1500MHz	14h	Hit	—
2SC453	Si-N	HF-L, 90V, 1,2A, 25W, 170MHz	49a	Mit	—
2SC4531	Si-N+Di	TV-HA, 1500/800V, 10A, 50W	18c	Tos	BU2520AF, (2SC3684)
2SC4532	Si-N	TV-HA, hi-res, 1700/600V, 10A, 200W	77c	Tos	S3934, 2SC4880
2SC4533	Si-N	S-L, 500/400V, 3A, 30W, <1/3,3µ	17c	Mat	2SC4052, 2SC4160, 2SC4421
2SC4536	Si-N	SMD, VHF/UHF, 30V, 0,25A	39b	Nec	BFQ84
2SC4537	Si-N	=2SC3513: SMD	35a(2mm)	Hit	—
2SC4538(R)	Si-N	S-L, 900/800V, 5A, 80W, <1µ/4,8µs	18c	Fjd	BUW11(A)F, 2SC4300, 2SC4427, 2SC4588, ++
2SC4539	Si-N	SMD, S, Io-sat, 50V, 1,2A, 100/400ns	39b	Tos	2SC4409, 2SD1623
2SC454(L)	Si-N	AM/FM-ZF, 30V, 0,1A, 230MHz, 1=ra	9b,7c	Hit	BF240..241, BF254..255, BF594..595, ++
2SC4540	Si-N	SMD, S, Io-sat, 80V, 1A, 100/500ns	39b	Tos	2SC4409
2SC4541	Si-N	SMD, S, Io-sat, 60V, 3A, 100/600ns	39b	Tos	—
2SC4542	Si-N	TV-HA, hi-res, 1500/600V, 10A, 50W	16c	Tos	BU2520AF

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2SC4543	Si-N	=2SC3526(H):SMD	39b	Mat	—
2SC4544	Si-N	HA-Tr, Chroma-E, 300V, 0,tA, 8W, 70MHz	17c	Tos	2SC3565, 2SC3942, 2SC3945, 2SC4075
2SC4545	Si-N	NF-E, 50V, 1,5A, 1,5W, t50MHz	78b	Mat	—
2SC4546	Si-N	S-Reg, 600/400V, 7A, 30W, <500/2150ns	17c	Sak	BU306F, BUT22BF..CF, 2SC4056
2SC4547	Si-N-Darl+Di	+Z-Di, 85/85V, 3A, 30W, 50MHz, B>2000	17j	Say	—
2SC4548	Si-N	=2SC4002:SMD	39b	Say	2SD1473
2SC4549	Si-N	=2SC3691	t7c	Nec	→2SC3691
2SC455	Si-N	AM/FM-ZF, 230MHz	9b	Hit	BF240..241, BF254..255, BF594..595,++
2SC4550	Si-N	=2SC3692	17c	Nec	→2SC3692
2SC4551	Si-N	=2SC3693	17c	Nec	→2SC3693
2SC4552	Si-N	=2SC3694	17c	Nec	→2SC3694
2SC4553	Si-N+Di	hi-beta, lo-sat, t00V, 7,5A, 30W, 100MHz	t7c	Nec	—
2SC4554	Si-N-Di	hi-beta, lo-sat, 100V, t5A, 30W, 100MHz	17c		—
2SC4555	Si-N	SMD, lo-sat, 20V, 0,5A, 300MHz	35a(2mm)	Say	—
2SC4557	Si-N	S-Reg, 900/550V, 10A, 80W, <t/5,5µs	18c	Sak	BUV48AFI, BUW13AF, 2SC4567
2SC4556	Si-N	hi-beta, lo-sat, 100V, 6A, 30W, B>700	17c	Sak	2SC4553
2SC4559	Si-N	S-L, 500/400V, 7A, 40W, <1/3,3µs	t7c	Mat	BU306F, 2SC4056, 2SC4130, 2SC4161
2SC456	Si-N	HF-A/Tr, 50V, 0,6A, 0,75W, 200MHz	2a	Mat	BFS23, BLY34
2SC4560	Si-N	HA, hi-res, 1500/600V, 10A, 80W	77j	Tos	BU2525A, 2SC3688
2SC456t	Si-N	SMD, Uni, 50V, 0,05A, 250MHz	85a	Mat	BC848..847, BCW71..72, BCW81,++
2SC4582	Si-N	=2SC4561:	85a(2mm)	Mat	2SC4081, 2SC4t28, 2SC4t41, 2SC4155,++
2SC4563	Si-N	Vid-E, hi-del, 100V, 0,6A, 10W, 1200MHz	44b	Say	2SC4479
2SC4564	Si-N	Vid-E, hi-del, 200V, 0,3A, 10W, 400MHz	14b	Say	2SC4623
2SC4565	Si-N	Vid-E, hi-del, 140V, 0,5A, t0W, 500MHz	14b	Say	—
2SC4566	Si-N	=2SC4564:20W	17j	Say	—
2SC4587	Si-N	=2SC4565:20W	17j	Say	—
2SC4588	Si-N	SMD, UHF-M/O, 20V, 30mA, 5GHz	35a	Nec	BFR93, 2SC3011
2SC4569	Si-N	SMD, UHF-M/O, 20V, 60mA, 5GHz	35a	Nec	BFR193, 2SC3161, 2SC3774..75
2SC457	Si-N	Dual, 25V, 0,05A, 0,3W, 200MHz	TO 60	Nec	—
2SC4570	Si-N	=2SC4568:	35a(2mm)	Nec	—
2SC457t	Si-N	=2SC4569:	35a(2mm)	Nec	—
2SC4572	Si-N	S-L, 600/800V, 20mA, 40MHz	t7j	Say	2SC4257, 2SC4451
2SC4573	Si-N-Darl+Di	Z-Di(B→C), 60V, 4A, 35W, B>2000, 60MHz	15c(H)	Rhm	2SD2024, (BDW23A..C, BDW53A..D,++)
2SC4574	Si-N-Darl+Di	=2SC4573:Iso, 30W	t5c(H)	Rhm	2SD1595, 2SD1891
2SC4575	Si-N-Darl+Di	=2SC4573:Iso	t5c(H)	Rhm	—
2SC4576	Si-N	S-L, 1400/700V, 0,3A, 20W, <2/4µs	t7j	Mat	2SC3676
2SC4577	Si-N	=2SC4555:	35a(3mm)	Say	2SC3265
2SC4578	Si-N	S-L, t700/900V, 50mA, 6MHz	t7j	Say	—
2SC4579	Si-N	S-L, 2000/900V, 20mA, 6MHz	17j	Say	2SC4913
2SC456(K,L,LG)	Si-N	Uni, 30V, 0,1A, 0,2W, 230MHz	9b,7c	Hit	BC169, BCt84, BC239, BC549, 2SC2675+
2SC4580	Si-N	S-L, 600/450V, 8A, 50W, 20MHz	18c	Shi	BUP22BF..CF, BUV47FI, AFI, BUW12F, AF
2SC4581	Si-N	S-L, 600/450V, 10A, 65W, 20MHz	18c	Shi	BUP23BF..CF, BUV48FI, AFI, BUW13F, AF
2SC4582	Si-N	S-L, 600/450V, 15A, 75W, 20MHz	18c	Shi	BUP23BF..CF, BUV48FI, AFI, BUW13F, AF
2SC4583	Si-N	S-L, 1200/800V, 3A, 50W, <500/3800ns	18c	Shi	BU705F, 2SD1543, 2SD1653
2SC4584	Si-N	S-L, t200/800V, 6A, 65W, <500/3800ns	18c	Shi	BU508AF, 2SC3885, 2SC3895, 2SC4144
2SC4565	Si-N	S-L, t200/800V, 10A, 85W, <500/3800ns	18c	Shi	BUH715, 2SC3897, 2SD1548
2SC4588	Si-N	S-L, 900/800V, 6A, 65W, <500/3500ns	18c	Shi	BU428AF, BUV47AF, BUW12AF, 2SC4428
2SC4587	Si-N	S-L, 900/800V, 10A, 75W, <500/3500ns	18c	Shi	BUV48AF, BUW13AF, 2SC4430
2SC4589	Si-N	CTV/Display-HA, 1500/800V, 10A, 50W	≈18c	Hit	2SC3897, 2SC4199A, 2SC4542
2SC459	Si-N	Uni, 30V, 0,tA, 0,2W, 230MHz	9b	Hit	BC188, BC183, BC239, BC548, 2SD767++
2SC459t	Si-N	SMD, VHF/UHF, 15V, 50mA, 9000MHz	35a	Hit	2SC3583, 2SC3904
2SC4592	Si-N	=2SC4591:9500MHz	44u	Hit	2SC4084, 2SC4127
2SC4593	Si-N	=2SC459t:	35a(2mm)	Hit	2SC4901
2SC4594	Si-N	S, 70V, 0,5A, 0,9W, <45/70ns	7c(9mm)	Hit	(2N4014)
2SC4595	Si-N	S-L, lo-sat, t00/60V, 12A, 30W, 120MHz	17c	Rhm	2SC4552
2SC4596	Si-N	S-L, lo-sat, 100/60V, 5A, 25W, 120MHz	17c	Rhm	2SC3540, 2SC4549
2SC4597	Si-N	S-Reg, 500/400V, 4A, 40W, 20MHz	30c	Say	2SC4219, (BUV46(A), BUT11(A), 2SC3497)
2SC4598	Si-N	S-Reg, 500/400V, 7A, 50W, 20MHz	30c	Say	2SC4220, (BUT54, BUT56(A), 2SC4055,+)
2SC4599	Si-N	S-Reg, 600/500V, 3A, 40W, 18MHz	30c	Say	2SC4171, 2SC4221, (BUT11(A), BUV46(A))
2SC46	Si-N	HF/S, 60V, 0,3A, 0,6W, 160MHz	2a	Fui	BFX55, BSW5t..52, 2N2218..19,++
2SC460	Si-N	AM-V/M/O/ZF, 30V, 0,1A, 230MHz	9b,7c	Hit	BF240..241, BF254..255, BF594..595,++
2SC4600	Si-N	S-Reg, 600/500V, 5A, 50W, 18MHz	30c	Say	2SC4172, 2SC4222, (BUT11(A), BUV46(A))
2SC4601	Si-N	S-Reg, 1100/800V, 1,5A, 40W, t5MHz	30c	Say	2SC4223, (2SC3178, 2SC3456)
2SC4602	Si-N	S-Reg, 1100/800V, 3A, 50W, 15MHz	30c	Say	2SC4224, (2SC3050, 2SC3457)
2SC4603(R)	Si-N	S-L, 900/800V, 3A, 60W, <tµ/4,8µs	t8c	Fjd	BUW11(A)F, 2SC4300, 2SC4299, 2SC4445,++
2SC4604	Si-N	NF/S, 60V, 3A, 0,9W, 100MHz	7c(9mm)	Tos	—

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2SC4605	Si-N	=2SC4479	17c	Tos	—
2SC4606	Si-N	=2SC1509	9c	Mat	→2SC1509
2SC4607	Si-N-Darl+Di	S-L, 1500V, 10A, 120W, 300/2160ns, B>5	18j	Mat	—
2SC4608	Si-N	HA, hi-res, 1700/600V, 8A, 200W	77j	Tos	S3934..35, 2SC4532
2SC461	Si-N	FM-V/M/O, 30V, 0,1A, 230MHz	9b,7c	Hit	BF241, BF255, BF314, BF502, BF505++
2SC4612	Si-N	S, 180/160V, 0,7A, 1W, 50/1060ns	9c	Say	2SC3332, 2SC4614
2SC4613	Si-N	S, 180/160V, 0,7A, 1W, 50/1060ns	14b	Say	2SC3902, (2SC3116..17)
2SC4614	Si-N	S, 180/160V, 1,5A, 1W, 40/1280ns	9c	Say	(2SD1812)
2SC4615	Si-N	S-L, 400/400V, 1A, 15W, 70MHz	30j	Say	2SC3362, 2SC3632, 2SD1053
2SC4616	Si-N	S-L, 400/400V, 2A, 15W, 60MHz	30j	Say	2SC3233, 2SC3631
2SC4617	Si-N	=2SC2412:	35a(1,6mm)	Rhm	2SD2216
2SC4618	Si-N	=2SC2413K	35a(1,6mm)	Rhm	2SC4915, 2SC5021
2SC4619	Si-N	=2SC3082K	35a(1,6mm)	Rhm	2SC4809, 2SC5021
2SC462	Si-N	TV-ZF, 40V, 0,05A, 600MHz	5g	Hit	BF198..199, BF224..225, BF310..311,++
2SC4620	Si-N	=2SC4295(M): Pins = 14mm	9c	Rhm	→2SC4295
2SC4621	Si-N	S-L, 500/400V, 7A, 70W, 30MHz	16c	Mat	BUP22BF..CF, BUV47FI, AFI, BUW12FAF
2SC4622	Si-N	S-L, 500/400V, 7A, 50W, <1/3µs	17j	Fjd	BUT54, BUT56(A), 2SC4106, 2SC4055, ++
2SC4623	Si-N	Vid-E, hi-def, 250V, 0,3A, 10W, 400MHz	14b	Say	—
2SC4626	Si-N	=2SC2295	35a(1,6mm)	Mat	2SC4656
2SC4627	Si-N	=2SC2404	35a(1,6mm)	Mat	2SC4655, 2SC4915, 2SC5021
2SC4628	Si-N	UHF, 20V, 20mA, 0,2W, >600MHz	7c	Hit	BF377..78, 2SC2498, 2SC2570(A), 2SC3777
2SC4629	Si-N	UHF, 15V, 50mA, 0,6W, 6000MHz	7l	Hit	2SC3355, (2SC2590(A), 2SC3512)
2SC463(H)	Si-N	VHF-re, 40V, 0,05A, 600MHz	5g	Hit	BF225, BF310, BF314, BF502, BF505++
2SC4630	Si-N	=2SC3675: Iso	17c	Say	—
2SC4631	Si-N	=2SC3676: Iso	17c	Say	—
2SC4632	Si-N	=2SC4256: Iso	17c	Say	(2SC4450)
2SC4633	Si-N	=2SC4257: Iso	17c	Say	(2SC4451)
2SC4634	Si-N	=2SC4450: Iso, 10mA	17c	Say	2SC4632
2SC4635	Si-N	=2SC4451: Iso, 20mA	17c	Say	2SC4633
2SC4636	Si-N	=2SC4475: Iso, 10mA	17c	Say	—
2SC4637	Si-N	=2SC4476: Iso, 15mA	17c	Say	—
2SC4636	Si-N	S-L, 800/500V, 5A, 40W, <1/4µs	17c	Mat	BUT11(A)F, 2SC3353, 2SC3795(A)
2SC4639	Si-N	=2SC4640: SMD	35a	Say	BC846, BCV71..72, 2SC3323, 2SC4076, ++
2SC464	Si-N	TV-ZF, 30V, 0,02A, 1100MHz	5g	Hit	BF198..199, BF224..225, BF310..311,++
2SC4640	Si-N	Uni, 55V, 0,15A, 0,3W, 200MHz	40c	Say	BC174, BC182, BC546, 2SC3245(A), ++
2SC4641	Si-N	=2SC4640: 0,5W	7c	Say	BC174, BC182, BC546, 2SC3245(A), ++
2SC4642K	Si-N	SMD, Uni, 50V, 0,1A, 180MHz	35a	Rhm	BC850, BCW71..72, 2SC3323, 2SC4076, ++
2SC4643	Si-N	=2SC4629: SMD	39b	Hit	2SC3301
2SC4644	Si-N	=2SC4002: 1W	9c	Say	→2SC4002
2SC4645	Si-N	S, Tr, 400/400V, 1A, 1W, 70MHz	9c	Say	—
2SC4646	Si-N	S, Tr, 400/400V, 2A, 1W, 60MHz	9c	Say	—
2SC4647	Si-N	NF, Vid, 300/300V, 0,1A, 0,4W, >50MHz	7c	Hit	BF393, BF420A, 2SC3468, 2SC4218, ++
2SC4648	Si-N	=2SC4594: 0,5W	7c	Hit	2N4014
2SC4649	Si-N	=2SC2059K:	35a(1,6mm)	Rhm	—
2SC465	Si-N	VHF/UHF, 30V, 0,02A, 1100MHz	5g	Hit	BF377..378, BF689, BF763, 2N2857, ++
2SC4650	Si-N	CRT, hi-def, 200/200V, 0,1A, 1W, 150MHz	9c	Say	2SC3467..68
2SC4652	Si-N	NF/S-L, -/120V, 8A, 80W	19c	Rhm	2SC4366, 2SC4690, 2SC5100
2SC4653	Si-N	NF/S-L, -/60V, 12A, 80W	16c	Rhm	2SC3762, 2SC4886
2SC4655	Si-N	=2SC2778:	35a(1,6mm)	Mat	2SC4627, 2SC4915, 2SC5021
2SC4656	Si-N	=2SC4561:	35a(1,8mm)	Mat	—
2SC4657	Si-N	S-L, 60V, 5A, 15W, 120MHz, 100/1100ns	≈30c	Tos	(2SC3518, 2SC3592, 2SD1603, 2SD1805)
2SC4658	Si-N	S-L, 100V, 5A, 15W, 120MHz, 200/1100ns	≈30c	Tos	(2SC3303, 2SC4332)
2SC4659	Si-N	S-L, 500/400V, 5A, 15W, <1/3,5µs	≈30c	Tos	(2SC4346)
2SC468(H)	Si-N	VHF/UHF, 30V, 0,02A, 1100(H=750)MHz	5g	Hit	BF377..378, BF689, BF763, 2N2857, ++
2SC4660	Si-N	Vid-E, hi-def, 30V, 0,3A, 8W, 2200MHz	14b	Say	—
2SC4661	Si-N	SMD, UHF, 15V, 35mA, 5000MHz	35a(2mm)	Mat	—
2SC4662	Si-N	S-L, 500/400V, 5A, 30W, <1/3,5µs	17c	Sak	2SC3669, 2SC4026, 2SC4371, 2SC4418, ++
2SC4663	Si-N	S-L, 250/200V, 5A, 25W, <300/1100ns	17j	Shi	BUT11(A), MJE51T..53T, 2SC2767,++
2SC4664	Si-N	S-L, 250/200V, 8A, 30W, <300/1100ns	17j	Shi	BU409, BUT11(A), TIP150..152
2SC4666	Si-N	SMD, ra, lo-sat, hi-beta, 50V, 0,15A, 250MHz	35a(2mm)	Tos	—
2SC4687	Si-N	SMD, S, 40V, 0,2A, 400MHz, 70/45ns	35a(2mm)	Tos	2SC4175..76
2SC4668	Si-N	S-L, lo-sat, 60V, 7A, 10W, <300/2000ns	30j	Shi	2SD1804
2SC4669	Si-N	S-L, lo-sat, 60V, 10A, 10W, <300/2000ns	30j	Shi	—
2SC467	Si-N	Uni, 20V, 0,05A, 0,3W	2a	Fuj	BC168, BC163, BC238, BC548, 2SC1890+
2SC4670	Si-N	=2SC4236:	35a(2mm)	Mat	2SC4780
2SC4671	Si-N-Darl+Di	int. Z-Di(B→C), 50V, 2A, 1W, B>1000	9c	Say	—

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2SC4672	Si-N	SMD, lo-sat, 60/50V, 2A, 210MHz	39b	Rhm	2SC4521, 2SD1623..24, 2SC4409
2SC4673	Si-N	UHF, 20V, 0,1A, 0,4W, 4500MHz		Say	—
2SC4674	Si-N	SMD. UHF, 12V, 8mA, 6000MHz	35a(2mm)	Hi1	—
2SC4675	Si-N	S-L, lo-sat, 30V, 8A, 10W, 250MHz	14b	Say	—
2SC4678	Si-N	HDTVChroma-E, 300V, 0,05A, 10W, 240MHz	17c	Tos	—
2SC4679	Si-N	=2SC4678 6W	14b	Tos	2SC3769..90, (2SC3417, 2SC3503, 2SC4826
2SC466(H)	Si-N	HF/S, 30V, 0,8A, 0,2W, 450MHz	2a	Hit	BSS11, BSX19..20, 2N2368..69(A), ++
2SC4680	Si-N	SMD, VHF/UHF, 12V, 50mA	35a	Hit	—
2SC4681	Si-N	Strobo, lo-sat, 30V, 3A, 10W, 150MHz	30j	Tos	2SC3074, 2SD1802, 2SD1805
2SC4682	Si-N	hi-beta, lo-sat, 30V, 3A, 0,9W, 150MHz	7c(9mm)	Tos	—
2SC4683	Si-N	=2SC4682: 1W	9c	Tos	—
2SC4684	Si-N	hi-beta, lo-sat, 50V, 5A, 10W, 150MHz	30j	Tos	2SD1719, 2SD1755
2SC4665	Si-N	=2SC4684:	14b	Tos	—
2SC4686	Si-N	Dynamic Focus, 1500/1000V, 0,05A, 10W	17c	Tos	2SC4630, (2SC4576)
2SC4668A	Si-N	<2SC4666: 1500/1200V	17c		(2SC4578)
2SC4687	Si-N	S-L, 500/400V, 7A, 70W, 30MHz	18j	Mat	BUV47(A), BUW12(A), TIP48A, 2SC3040++
2SC4686	Si-N	HiFi-NF-E, 80V, 6A, 55W, 30MHz	18c	Tos	2SC4385, 2SC5099, 2SD2064, (BD245A..F)
2SC4689	Si-N	HiFi-NF-E, 120V, 6A, 70W, 30MHz	18c	Tos	2SC4386, 2SC5100, 2SD2052, (BD245C..F)
2SC469	Si-N	FM-ZF, 20V, 0,03A, 250MHz	24b	Nec	(BF240, BF254, BF494, BF594,++)
2SC4690	Si-N	HiFi-NF-E, 140V, 10A, 80W, 30MHz	18c	Tos	2SC4387, 2SC5101, 2SC4888, (BD245D..F)
2SC4691	Si-N	=2SC3757:	35a(1,6mm)	Mat	—
2SC4692	Si-N	TV-HA, 1500/800V, 12A, 50W	≈18c	Hit	BU2525AF
2SC4693	Si-N	VHF, 30V, 0,3A, 0,9W, 2500MHz	7c(9mm)	Hit	(2SC4308)
2SC4694	Si-N	=2SC4695:	35a(2mm)	Say	2SD1949, 2SD1979, 2SD1820A
2SC4695	Si-N	SMD, NF/S, 50V, 0,5A, 250MHz	35a(3mm)	Say	BC817, BCW65, BCX19, 2SC3325, ++
2SC4696	Si-N-Darl+Di	+Z-Di(B→C), 80/80V, 0,8A, 1W, B>1000	9c	Say	BC677, BC879, BSR51..52, 2SD1153,++
2SC4699K	Si-N	SMD, NF/S, 25V, 0,2A, 250MHz, <50/40ns	35a	Rhm	2SC1621, 2SC4894
2SC47	Si-N	=2SC46: 40V, 0,72A	2a	Fui	BFX55, BSW51..52, 2N2218..19,++
2SC470(-3..-6)	Si-N	HF/Vid. 90180V, 0,1A, 0,75W, 150MHz	2a	Son	BF257..259, BF657..659, 2N5058..59
2SC4700	Si-N	=2SC4669K:	35a(2mm)	Rhm	2SC4175..78, 2SC4755
2SC4702	Si-N	SMD, NF, Vid, 300/300V, 0,05A, 60MHz	35a	Hit	BFN26, 2SC4061, 2SC4497
2SC4703	Si-N	SMD, UHF, 25V, 0,15A, 6GHz	39b	Nec	—
2SC4704	Si-N	Vid-E, 200/200V, 0,2A, 10W, 300MHz	14h	Hi1	2SC3801
2SC4705	Si-N	SMD, hi-beta, 80V, 0,2A, 250MHz, B>600	39b	Say	2SC3651
2SC4706	Si-N	S-L, 900/600V, 14A, 130W, 6MHz	18j	Sak	BUV48(A), BUW13(A), BUW133(A)
2SC4707	Si-N	NF/S, 35V, 0,5A, 0,6W, 300MHz	7c(9mm)	Tos	2SC3939, 2SC4414 2SD1211, 2SD1837
2SC4706	Si-N	Display-Video, 100V, 0,2A, 5W, 1,1GHz	14h	Hit	2SC3598, 2SC3599
2SC4709	Si-N	TV, Dynamic Fokus, 2100/2100V, 10mA	17j	Say	(2SC4476)
2SC471(H)	Si-N	Uni, 30V, 0,1A, 0,2W, 180MHz	2a	Hit	BC188, BC183, BC238, BC548, 2SD767++
2SC4710(LS)	Si-N	=2SC4709: Iso	17c	Say	(2SC4637)
2SC4713K	Si-N	SMD, HF/S, 12V, 0,05A, 800MHz, Ron=2Ω	35a	Rhm	—
2SC4714	Si-N	CTV-Chroma, 300/300V, 0,1A, 15W, 140MHz	17j	Ma1	2SC1929
2SC4715	Si-N	Uni, Ra, 150V, 0,05A, 0,3W, 160MHz	40c	Ma1	2SC2362K, 2SC2631..2632, 2SC3800
2SC4716	Si-N	VHF-O, 30V, 0,05A, 0,3W, >600MHz	40c	Mat	BF314, BF503, BF505, 2SC1856, 2SC3354
2SC4719	Si-N	Uni, -/32V, 1A, 0,9W	7c(9mm)	Rhm	2SC4145, 2SD1207, 2SD1292, 2SD1616,++
2SC472(H)	Si-N	=2SC471: 180MHz, <100/500ns	2a	Hi1	BC166, BC183, BC238, BC548, 2N3904++
2SC4720	Si-N	Uni, -/150V, 0,05A, 0,8W	7c(9mm)	Rhm	BF298, BF422A, 2SC3248, 2SC3467
2SC4721	Si-N	NF-Tr/E, -/50V, 2A, 0,9W	7c(9mm)	Rhm	2SC4145, 2SD1207, 2SD2485
2SC4722	Si-N	Vid/S, -/300V, 0,1A, 0,9W	7c(9mm)	Rhm	BF420A, 2SC3468..69, 2SC4168
2SC4723	Si-N	=2SC4642:	35a(2mm)	Rhm	2SC4081, 2SC4128, 2SC4155, 2SC4177, ++
2SC4724	Si-N-Darl+DI	-/100V, 3A, 1,2W, B>2k	78b	Say	2SC4339
2SC4725	Si-N	=2SC3837K:	35a(1,6mm)	Rhm	—
2SC4726	Si-N	=2SC3838K:	35a(1,6mm)	Rhm	—
2SC4727	Si-N	S-L, 30V, 8A, 250MHz, 30/265ns	≈12b	Say	—
2SC4726	Si-N	S-L, 80V, 5A, 160MHz, 50/520ns	≈12b	Say	—
2SC4729	Si-N	S-L, 80V, 8A, 160MHz, 50/520ns	≈12b	Say	—
2SC473(H)	Si-N	=2SC471: 70V, 180MHz, <80/200ns	2a	Hit	BC174, BC182, BC190, BC546, 2N2222A+
2SC4730	Si-N	S-L, 120V, 3A, 180MHz, 100/950ns	≈12b	Say	—
2SC4731	Si-N	S-L, 120V, 4A, 160MHz, 100/950ns	≈12b	Say	—
2SC4732	Si-N	=2SC3416:	≈12b	Say	(2SC3502, 2SC3955, 2SC3600..01, 2SC3786)
2SC4733	Si-N	=2SC3417:	≈12b	Say	(2SC3417, 2SC3503, 2SC3769..90, 2SC4626)
2SC4734	Si-N	S, 400/400V, 2A, 1,5W, 60MHz	≈12b	Say	—
2SC4735	Si-N	AM/FM-E, 27MHz-CB, 75V, 1A, 250MHz	≈12b	Say	—
2SC4736	Si-N	hi-beta, 80V, 2A, 170MHz, B>800	≈12b	Say	(2SC3474, 2SD1754..55)
2SC4737	Si-N-Darl	S, 50V, 2A, 200/4000ns, B>1000	≈12b	Say	(BD677, BD679, 2SD1759, 2SD1617,++)
2SC4738	Si-N	SMD, NF, ra, 80V, 0,15A, >80MHz	35a(1,6mm)	Tos	2SD2216

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2SC474(H)	Si-N	=2SC471: 70V,<100/500ns	2a	Hit	BC174, BC182, BC190, BC546, 2N2222A+
2SC4740	Si-N	CTV/Display-HA, 1500/800V, 8A, 50W	23a	Hit	BU508A, BU2508A, 2SC3027..28, 2SC4901+
2SC4741	Si-N	CTV/Display-HA, 1500/800V, 10A, 50W	23a	Hit	BU2520A, 2SC3688
2SC4742	Si-N+Di	Display-HA, 1500V, 6A, 50W	18j	Hit	BU508D, 2SC3482, 2SC3682, 2SC4292
2SC4743	Si-N	Display-HA, 1500/800V, 8A, 50W	18j	Hit	BU508A, BU908, 2SC3486, 2SC3686
2SC4744	Si-N+Di	=2SC4742: Iso	≈18c	Hit	BU508DF, 2SC4294, 2SD1556, 2SD1652
2SC4745	Si-N	=2SC4743: Iso	≈18c	Hit	BU508AF, 2SC4143, 2SD1546, 2SD1656
2SC4746(A)	Si-N	=2SC4740: Iso	≈18c	Hit	BU508AF, 2SC3888A, 2SC3896, 2SC4797
2SC4747	Si-N	=2SC4741: Iso	≈18c	Hit	2SC4199A, 2SC4569
2SC475	Si-N	=2SC478 ra	24b	Nec	(BC189, BC184, BC239, BC549, 2SC2675,++)
2SC4750	Si-N	S-L, 500/400V, 15A, 80W, <500/1650ns		Fjd	—
2SC4754	Si-N	S-L, 900/400V, 2A, 20W, <1/3,5µs	30j	Tos	2SC4171, 2SC4221, (BUT93, BUX84,+)
2SC4755	Si-N	SMD, SS, 25V, 0,2A, 500MHz, 17/15ns	35a(2mm)	Mat	2SC4175..78, 2SC4452
2SC4757	Si-N	Display-HA, hi-res, 1500/900V, 7A, 50W	18c	Tos	2SC3885A, 2SC3895
2SC4756	Si-N	Display-HA, hi-res, 1500/600V, 8A, 50W	18c	Tos	2SC3888A, 2SC3896
2SC4759	Si-N	Display-HA, C4970hi-res, 1500/800V, 10A, 50W	18c	Tos	BUH715, BU2520AF, 2SC4542
2SC478	Si-N	Min, NF-Tr, 20V, 0,1A, 0,15W, 100MHz	24b	Nec	(BC168, BC183, BC238, BC548, 2SD787,++)
2SC4780	Si-N	Display-HA, hi-res. 2000/800V, 8A, 200W	77j	Tos	—
2SC4761	Si-N	Display-HA, hi-res, 1700/600V, 8A, 50W	18c	Tos	BUH417, BUH517, 2SC4806
2SC4782	Si-N+Di	Display-HA, VGA, 1500/600V, ±7A, 50W	18c	Tos	2SC3892A
2SC4763	Si-N+Di	Display-HA, VGA, 1500/600V, ±8A, 50W	18c	Tos	BU2520DF, 2SC3893A
2SC4764	Si-N+Di	Display-HA, VGA, 1500/600V, ±8A, 50W	18c	Tos	2SC3892A
2SC4765	Si-N+Di	Display-HA, VGA, 1700/600V, ±5A, 50W	18c	Tos	BUH517D, 2SC4962
2SC4766	Si-N+Di	Display-HA, VGA, 1700/600V, ±6A, 50W	18c	Tos	BUH517D, 2SC4982
2SC4767	Si-N	VHF-Tr/E, 38V, 0,3A, 1W, >1500MHz	7c(9mm)	Mat	—
2SC4768	Si-N	S-L, 450/400V, 10A, 80W, <1/3µs	18j	Tos	2SC2625, 2SC2740, 2SC3042, 2SC4138, ++
2SC4769	Si-N+Di	=2SC4770: int. Damper-Diode	18c	Say	BU508DF, 2SC3893A, 2SC4123..24, 2SD2251
2SC477	Si-N	HF, 50V, 0,03A, 0,14W, 230MHz	2a	Mat, Mic	BF240..41, BF254..255, BF594..595,++
2SC4770	Si-N	HA, 1500/800, 7A, 80W	18c	Say	2SC3885A, 2SC3895, 2SD2252
2SC4771K	Si-N	SMD, HF, 30V, 0,05A, 800MHz	35a	Rhm	BF599, BF799, 2SC3130, 2SC3374,++
2SC4772	Si-N	=2SC4771K:	35a(2mm)	Rhm	BF547W, BFS17W, 2SC3932, 2SC3935
2SC4773	Si-N	=2SC43281K	35a(2mm)	Rhm	BF547W, BFS17W, 2SC3933, 2SC4780
2SC4774	Si-N	=2SC4713K:	35a(2mm)	Rhm	—
2SC4775	Si-N	=2SC4642: 0,4W	9c	Rhm	BC167, BC182, BC237, BC547,++
2SC4776M	Si-N	=2SC4642: 0,4W	9c	Rhm	BC187, BC182, BC237, BC547,++
2SC4777	Si-N	=2SC4642: 0,4W, Pins=14mm	9c	Rhm	BC187, BC182, BC237, BC547,++
2SC4778	Si-N	=2SC4642: 0,4W, Pins=14mm	9c	Rhm	BC187, BC182, BC237, BC547,++
2SC4779S	Si-N	=2SC4642: 0,3W	41c	Rhm	BC187, BC182, BC237, BC547,++
2SC478	Si-N	Uni, 50V, 0,12A, 0,3W, 180MHz	2a	Mat	BC167, BC182, BC237, BC547, 2SD787++
2SC4780	Si-N	SMD, UHF, 25V, 50mA, 4500MHz	35a(2mm)	Mat	—
2SC4781	Si-N	Strobo, lo-sat, 30V, 4A, 0,9W, 170MHz	7c(9mm)	Tos	2SC4482, 2SD1145
2SC4782	Si-N	=2SC4755:	35a	Mat	2SC1621, 2SC4453
2SC4783	Si-N	SMD, NF, 80V, 0.1A, 150MHz	35a(1,6mm)	Nec	2SC4738, 2SC4617
2SC4764	Si-N	SMD, VHF/UHF, 15V, 20mA, 10GHz	35a(2mm)	Hit	BFS505, 2SC5095
2SC4768	Si-N	S-L, 900/500V, 5A, 40W, >20MHz	18c	Fjd	BUW11AF, 2SC3400, 2SC4427, 2SC4586,++
2SC4787	Si-N	TV-ZF, 45V, 50mA, 0,6W, >300MHz	9c	Mat	BF921S, BF959
2SC4789	Si-N	Display-HA, 1500/800V, 25A, 150W	77j	Hit	2SC3998
2SC479(H)	Si-N	S, 80V, 0,8A, 0,65W, 30/55ns	2a	Hit	BSS13, BSV77, 2N5189, 2SC1072,++
2SC4791	Si-N	=2SC4[illegible]84:	44u	Hit	2SC5097
2SC4792	Si-N	SMD, VHF, 30V, 50mA, 800MHz	35a	Mat	BF799, 2SC3015, 2SC3374
2SC4793	Si-N	NF-L, 230/230V, 1A, 20W, 100MHz	17c	Tos	—
2SC4795	Si-N	S-L, 500/400V, 30A, 120W, <1/3µ	18j	Fjd	—
2SC4796	Si-N	Display-HA, 1700/900V, 6A, 50W	≈18c	Hit	BUH417, (2SD1434)
2SC4797	Si-N	Display-HA, 1700/900V, 8A, 50W	≈18c	Hit	BUH517
2SC4799	Si-N	S-L, 300/90V, 8A, 50W	18j	Hit	TIP55A..57A, 2SC2305, 2SC3813
2SC48	Si-N	=2SC46: 120V	2a	Fui	BSW67..68, BSY55..56, 2N1893,++
2SC490	Si-N	=2SC479: 0,8W, <30/40ns	2a	Hit	BSS13, BSV77, 2N5189, 2SC1072,++
2SC4800	Si-N	S-L, HA, 1500/800V, 5A, 80W	23a	Hit	BU208A, BU508A, 2SD1498, 2SC3685,++
2SC4801	Si-N	Display-HA, 1500/500V, 8A, 50W	23a	Hit	BU508A, BU908, BU2508A, 2SC3697,++
2SC4802	Si-N	Display-HA, 1700/800V, 5A, 50W	23a	Hit	2SC3026, 2SD784..95, 2SD1434
2SC4803	Si-N+Di	Display-HA, 1500/800V, 5A, 50W	23a	Hit	BU208D, BU508D, 2SD1171..75, 2SD1878++
2SC4805	Si-N	SMD, UHF, 15V, 65mA, >7GHz	85a(2mm)	Mat	BFS520, 2SC4901
2SC4808	Si-N	Display-HA, hi-res, 1700/600V, 5A, 50W	18c	Tos	BUH417, BUH517, 2SC4761
2SC4807	Si-N	SMD, VHF/UHF, 20V, 0,2A, 4,4GHz	39b	Hit	—
2SC4808	Si-N	=2SC3829:	35a(1,8mm)	Mat	—
2SC4808	Si-N	=2SC3130:	35a(1,6mm)	Mat	—

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2SC481	Si-N	AM/FM-Tr/E, 60V, 1A, PQ>1W(50MHz)	2a	Tos	BFS23, BLY34
2SC4810	Si-N-Darl+Di	S-L, 100V, ±5A, 500/3100ns, B>2000	78c	Nec	—
2SC4811	Si-N-Darl+Di	S-L, 100V, ±8A, 500/3100ns, B>2000	78c	Nec	—
2SC4812	Si-N-Darl+Di	S-L, 100V, ±10A, 500/3100ns, B>2000	78c	Nec	—
2SC4813	Si-N+Di	=2SC4553: 1,8W	78c	Nec	—
2SC4814	Si-N+Di	hi-beta, Io-sat, 100V, ±2,5A, 500/2500ns	78c	Nec	—
2SC4815	Si-N	Io-sat, 100V, 5A, 1,8W, 100/1250ns	78c	Nec	—
2SC4816	Si-N	Io-sat, 100V, 7A, 1,8W, 200/1400ns	78c	Nec	—
2SC4817	Si-N	Io-sat, 150V, 5A, 1,8W, <300/1900ns	78c	Nec	—
2SC4818	Si-N	Io-sat, 150V, 7A, 1,8W, <300/1900ns	78c	Nec	—
2SC4819	Si-N	Io-sat, 150V, 10A, 1,8W, <300/1900ns	78c	Nec	—
2SC482	Si-N	HF/Uni, 40V, 0,6A, 0,6W, >50MHz	2a	Tos	BC140..141, BC300..302, 2N2218..19,++
2SC4820	Si-N	S-Reg, 900/450V, 8A, 30W, <500/3800ns	17c	Sak	BUT12(A)F, BUT18(A)F, BUV46(A)FI
2SC4821	Si-N	=2SC3950: 1,3W	≈12b	Say	(→2SC3950)
2SC4822	Si-N	=2SC3951: 1,3W	≈12b	Say	(→2SC3951)
2SC4823	Si-N	=2SC3952: 1,3W	≈12b	Say	(→2SC3952)
2SC4824	Si-N	=2SC3953: 1,3W	≈12b	Say	(→2SC3953)
2SC4825	Si-N	=2SC3954: 1,3W	≈12b	Say	(→2SC3954)
2SC4826	Si-N	=2SC3955: 1,3W	≈12b	Say	(→2SC3955)
2SC4827	Si-N	=2SC3956: 1,3W	≈12b	Say	(→2SC3956)
2SC4828	Si-N	TV-Video, 300/300V, 0,1A, 8W, 80MHz	14b	Hit	2SC3271, 2SC4217, (BF417, BF459)
2SC4829	Si-N	Display-Video, 100V, 0,2A, 0,9W, 1,1GHz	7c(9mm)	Hit	—
2SC483	Si-N	NF/S-L, 100V, 1A, 15W, 25MHz	22a	Tos	BD239C, BD241C, 2SC1913, 2SC2275,++
2SC4830	Si-N	Display-HA, hi-res, 1500/600V, 8A, 50W	18c	Tos	2SC3884A, 2SC3894, 2SC4757
2SC4831	Si-N	S-L, 500/400V, 15A, 80W, <500/1650ns	18c	Fjd	—
2SC4833	Si-N	S-L, 500/400V, 5A, 35W, <300/1400ns	15c	Shi	BUT11(A)F, 2SC4054, 2SC4073, 2SC4371,++
2SC4834	Si-N	S-L, 500/400V, 6A, 45W, <300/1400ns	15c	Shi	BU306F, BUT12(A)F, 2SC4130, 2SC4161,+
2SC4835	Si-N	=2SC3829:	35a(2mm)	Mat	—
2SC4836	Si-N	S-L, 60/20V, 5A, 1,5W, 120MHz	≈12b	Say	2SD1903
2SC4837	Si-N	S-L, 60/50V, 4A, 1,5W, 150MHz	≈12b	Say	2SD1903
2SC4839	Si-N	=2SC3605: SMD	35a(1,6mm)	Tos	2SC5086
2SC484	Si-N	Uni, 150V, 1,5A, 0,8W, 20MHz	2a	Tos	BSS43, BSW68, 2SC1860
2SC4840	Si-N	=2SC4316: SMD	35a(1,6mm)	Tos	2SC5091
2SC4841	Si-N	=2SC4322:	35a(1,6mm)	Tos	2SC4840
2SC4842	Si-N	=2SC4315:	44u(2mm)	Tos	2SC5088
2SC4843	Si-N	=2SC4316: SMD	44u(2mm)	Tos	2SC5093
2SC4844	Si-N	=2SC4322: SMD	44u(2mm)	Tos	2SC4994, 2SC5098
2SC4845	Si-N	L, Io-sat, -/120V, 5A, 40W	17j	Rhm	2SC4326
2SC4846	Si-N	=2SC4845: Iso, 30W	17c	Rhm	2SD1270
2SC4847	Si-N	L, Io-sat, -/120V, 5A, 80W	16c	Rhm	(2SD2065)
2SC4848	Si-N	S-Reg, Io-sat, 250/120V, 7A, 40W, 20MHz	17j	Rhm	—
2SC4849	Si-N	=2SC4848: Iso, 30W	17c	Rhm	—
2SC485	Si-N	=2SC484: 100V	2a	Tos	BCX40, BSW66, BSX46, 2N3107..08,++
2SC4850	Si-N	L, Io-sat, -/120V, 7A, 60W	18c	Rhm	(2SD2065)
2SC4851	Si-N	=2SC4852:	35a(2mm)	Say	—
2SC4852	Si-N	SMD, hi-beta, 25V, 0,1A, 240MHz, Ron=0,9Ω	35a	Say	—
2SC4853	Si-N	SMD, VHF/UHF, 12V, 15mA, 5GHz	35a(2mm)	Say	BFR92W, BFR820W
2SC4854	Si-N	=2SC4853:	35a(3mm)	Say	BFR92, BFR820
2SC4855	Si-N	=2SC4853:	44u	Say	—
2SC4858	Si-N	=2SC4859:	35a(2mm)	Say	2SC3937
2SC4857	Si-N	=2SC4859:	35a(3mm)	Say	2SC3704, 2SC3445
2SC4856	Si-N	=2SC4859:	44u	Say	2SC4092
2SC4859	Si-N	SMD, VHF/UHF, 18V, 80mA, 5,5GHz	39b	Say	BFQ193, 2SC3607
2SC486	Si-N	=2SC484: 70V	2a	Tos	BCX40, BSW65, BSX45, 2N3109..10,++
2SC4860	Si-N	SMD, VHF/UHF, 20V, 30mA, 6,5GHz	35a(2mm)	Say	2SC3937
2SC4861	Si-N	=2SC4860:	35a(3mm)	Say	2SC3704, 2SC3445
2SC4862	Si-N	=2SC4860:	44u	Say	2SC3357, 2SC4092
2SC4863	Si-N	=2SC4866:	35a(2mm)	Say	2SC3937
2SC4864	Si-N	=2SC4866:	35a(3mm)	Say	2SC3704, 2SC3445
2SC4865	Si-N	=2SC4886:	44u(3mm)	Say	2SC4092
2SC4866	Si-N	SMD, VHF/UHF, 18V, 70mA, 6,5GHz	39b	Say	BFQ193, 2SC3301, 2SC3607
2SC4867	Si-N	SMD, VHF/UHF, 16V, 50mA, 9GHz	35a(2mm)	Say	2SC4593, 2SC4901
2SC4868	Si-N	=2SC4867:	35a(3mm)	Say	2SC3583, 2SC3904, 2SC4591
2SC4869	Si-N	=2SC4867:	44u	Say	2SC4094, 2SC4127, 2SC4900
2SC487	Si-N	NF/S-L, 110V, 1,5A, 15W, 20MHz	22a	Tos	BD239C, BD241C, 2SC2275, 2SC2528,++
2SC4870	Si-N	=2SC4867: 8GHz	39b	Say	2SC4643

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2SC4871	Si-N	SMD, VHF/UHF, 16V, 20mA, 10GHz	35a(2mm)	Say	BFS 505, 2SC5095
2SC4872	Si-N	=2SC4871:	35a(3mm)	Say	BFR 505, 2SC5094
2SC4873	Si-N	=2SC4871:	44u	Say	2SC5097
2SC4874	Si-N	VHF/UHF, 20V, 50mA, 5,8GHz	7f	Hit	2SC3512, 2SC4629
2SC4875	Si-N	VHF/UHF, 15V, 50mA, 8,5GHz	7f	Hit	2SC4829
2SC4876	Si-N	S-L, Io-sat, 60V, 30A, 45W, <0,3/2µs	15c	Shi	—
2SC4877	Si-N+Di	TV/Monitor-HA, 1500V, 8A, 50W	≈18c	Hit	BU2508DF, 2SC3893A 2SC4763, 2SD2371, ++
2SC4878	Si-N+Di	TV/Monitor-HA, 1500V, 10A, 50W	≈18c	Hit	BU2520DF, 2SC4125, 2SC4531, 2SD1881
2SC4879	Si-N	TV/Monitor-HA, 1700/900V, 10A 50W	≈18c	Hit	—
2SC487A	Si-N	=2SC487: 150V	22a		BD239D, 2SC2275A, 2SC2344, 2SC2529, ++
2SC488	Si-N	NF/S-L, 140V, 3A, 16W, 10MHz	22a	Tos	BD241D, BDV11, 2SC2516, 2SD772, ++
2SC4880	Si-N	TV/Monitor-HA, 1700/900V, 12A, 100W	≈18c	Hit	2SC4896
2SC4881	Si-N	S-L, Io-sat, 60V, 5A, 20W, 100/900ns	17c	Tos	2SC3299, 2SC3746, 2SC4549, 2SC4596
2SC4882	Si-N	S-L, Io-sat, 1200V, 5A, 60W, <2/4µs	18c	Mat	—
2SC4863	Si-N	TV, NF-L, 150/150V, 2A, 20W, 120MHz	17c	Sak	2SC3298, 2SC3364, 2SC4159, 2SD1763A
2SC4883A	Si-N	=2SC4883: 180/180V	17c		2SC3298A, B, 2SC4159
2SC4884	Si-N	Vid-E, 300/300V, 0,1A, 1,5W, 70MHz	≈12b	Say	(2SC1505..07, 2SC3952, 2SC3945, 2SC4075)
2SC4885	Si-N	UHF-O, 25V, 50mA, 2,5GHz	35a(2mm)	Nec	—
2SC4888	Si-N	NF/S-L, 150/150V, 14A, 80W, 60MHz	18c	Sak	2SC4388
2SC4887	Si-N	CRT-Display, 2500/1200V, 0,1A	17c	Say	—
2SC4888	Si-N	CRT-Display, 2500/1200V, 0,3A	17c	Say	—
2SC489	Si-N	=2SC488: 100V	22a	Tos	BD241C, BD243C, BD539C, BD937, ++
2SC4890	Si-N	CRT-HA, hi-res, 1500/800V, 12A, 75W	18c	Say	BU2525AF, BU2527AF, 2SC5105
2SC4891	Si-N	CRT HA, hi-res, 1500/800V, 15A, 100W	18c	Say	(BUH1015T)
2SC4892	Si-N	S-L, 900/800V, 1A, 15W, 4MHz, <1/4µs	78c	Mat	(BUX85F, 2SC3794A, 2SC3978)
2SC4894	Si-N	SMD, SS, 25V, 0,13A, 500MHz, 17/15ns	35a	Mat	2SC1621, 2SC4453
2SC4895	Si-N-Darl+Di	NF-L, 120/100V, 3/5A, 30W, 60MHz, B>2k	17c	Rhm	2SD1785, 2SD2014..2015
2SC4896	Si-N	TV/Monitor-HA, 1700/900V, 15A, 100W	77j	Hit	—
2SC4897	Si-N	TV/Monitor-HA, 1500/800V, 20A, 150W	77j	Hit	2SC3997, 2SC4290A, 2SD2356
2SC4896	Si-N	S-L, 1000/300V, 5A, 40W, 8MHz, <1,5/4µs	17c	Mat	BUT11AF, BUT18AF, BUV46AFI, 2SC4518A
2SC4899	Si-N	SMD, VHF/UHF, 15V, 20mA, 9GHz	35a(2mm)	Hit	BFS 505, 2SC5095
2SC49(M,N)	Si-N	HF/S, 120V, 0,3A, 0,8W, 160MHz	2a	Nec	BSW67..68, BSY55..56, 2N1893, ++
2SC490	Si-N	=2SC488: 60V	22a	Tos	BD241A, BD243A, BD539A, BD935, ++
2SC4900	Si-N	SMD, VHF/UHF, 15V, 50mA, 9GHz	44u	Hit	2SC4094, 2SC4127
2SC4901	Si-N	=2SC4900:	35a(2mm)	Hit	2SC4593
2SC4902	Si-N	SMD, VHF/UHF, 20V, 30mA, 6GHz	35a	Hit	BFR182, 2SC301t, 2SC5108
2SC4903	Si-N	=2SC4902:	35a(2mm)	Hit	BFR182W, 2SC5107
2SC4904	Si-N	SMD, VHF/UHF, 20V, 50mA, 5,8GHz	35a	Hit	BF770A, BFQ67, BFR183, 2SC3513
2SC4905	Si-N	=2SC4904:	35a(2mm)	Hit	BFR183W, BFQ67W
2SC4908	Si-N	=2SC4904:	35a(2mm)	Hit	BFR183W, BFQ67W
2SC4907	Si-N	S-Reg, 600/500V, 8A, 30W, 8MHz, <1/5µs	17c	Sak	BU306F, BUT22BF..CF, 2SC4056, 2SC4546
2SC4908	Si-N	S-Reg, 900/800V, 3A, 35W, 6MHz, <1/8µs	17c	Sak	2SC3559, 2SC4304, 2SC4517, 2SC4471A, ++
2SC4909	Si-N	SMD, Muting, hi-Ueb, 25V, 0,1A	35a(2mm)	Say	—
2SC491	Si-N	NF/S-L, 50V, 1,5A, 15W, 40MHz	22a	Tos	BD239, BD241, 2SC1398, 2SC3252, ++
2SC4910	Si-N	VHF-Tr, 39V, 0,75A, PO=0,9W(175MHz)	≈12b	Say	—
2SC4911K	Si-N	SMD, S, 20V, 0,2A, 450MHz	35a(3mm)	Rhm	2SC3735, 2SC4453
2SC4912	Si-N	=2SC4911K:	35a(2mm)	Rhm	2SC4175..76, 2SC4452
2SC4913	Si-N	S-L, 2000/2000V, 20mA, B>10	17j	Hit	—
2SC4915	Si-N	=2SC2714:	35a(1,6mm)	Tos	2SC4855, 2SC5021
2SC4916	Si-N+Di	Display-HA, hi-res, 1500/600V, ±7A, 50W	18c	Tos	2SC3892A, 2SC4762
2SC4917	Si-N	S-Reg, 600/400V, 2A, 10W, <1/3,5µs	14b	Rhm	(2SC3924)
2SC4918	Si-N	SMD, HF, FM, 40V, 0,05A, 750MHz	35a(1,6mm)	Say	—
2SC4919	Si-N	=2SC4852:	35a(1,6mm)	Say	—
2SC492	Si-N	NF/S-L, 110V, 5A, 50W	23a	Tos	BD245C, BDV95, 2N5759..60, 2SD718, ++
2SC4920	Si-N	SMD, Muting, 25V, 0,1A, 240MHz, Ron=2,2Ω	35a(1,6mm)	Say	—
2SC4921	Si-N	SMD, Muting, 25V, 0,1A, 240MHz, Ron=2,8Ω	35a(1,6mm)	Say	—
2SC4922	Si-N	SMD, Muting, 25V, 0,1A, 240MHz, Ron=4Ω	35a(1,6mm)	Say	—
2SC4923	Si-N	CRT HA, hi-res, 1500/800V, 8A, 70W	18c	Say	BU2520AF, 2SC3896, 2SC3886A, 2SC4758, ++
2SC4924	Si-N	CRT HA, hi-res, 1500/800V, 10A, 70W	18c	Say	BU2520AF, BUH715, 2SC4542, 2SC4759
2SC4926	Si-N	SMD, VHF/UHF, 15V, 50mA, 11GHz	44u	Hit	2SC4094, 2SC4127, 2SC4592
2SC4927	Si-N+Di	TV/Monitor-HA, 1500V, 8A, 50W	≈18c	Hit	BU2508DF, 2SC3893A, 2SC4763, 2SD2371, ++
2SC4928	Si-N	Monitor-HA, 1500/800V, 15A, 150W	77j	Hit	2SC3996, 2SC4289A
2SC4929	Si-N	SMD, S, 500/400V, 0,8A, 80MHz	39b	Mat	—
2SC493	Si-N	=2SC492: 60V	23a	Tos	BD245B, BDV93, 2N4915, 2SD985..988, ++
2SC4930	Si-N	SMD, VHF/UHF, 7GHz	35a(1,6mm)	Say	—
2SC4931	Si-N	SMD, VHF/UHF, 16V, 0,05A, 9GHz	35a(1,8mm)	Say	2SC5139

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2SC4934	Si-N	=2SC4046: Iso	14b	Hit	2SC3953, (2SC3598..99, 2SC4046)
2SC4935	Si-N	150V, 3A, 10W, 80MHz	17c	Tos	2SC3299, 2SC3690, 2SC3746, 2SD1762
2SC4937	Si-N	=2SC3968: 35W	30j	Rhm	—
2SC4936	Si-N	S-L, 400/400V, 5A, 35W, <1/3,5µs	30j	Rhm	2SC4220
2SC4939	Si-N	=2SC4595: 35W	30j	Rhm	—
2SC494	Si-N	=2SC492: 50V	23a	Tos	BD245A, BDV91, 2N4914..15, 2SD965, ++
2SC4940	Si-N	S-L, 1200/550V, 4A, 30W, <500/3300ns	15c	Shi	BU506F
2SC4941	Si-N	S-L, 1500/800V, 6A, 65W, <500/3800ns	18c	Shi	BU508(A)F, 2SC4303A, 2SC4770, 2SD2252++
2SC4942	Si-N	SMD, S, 600/600V, 1A, 30MHz, <0,5/5,5µs	39b	Nec	—
2SC4943	Si-N	=2SC4572: Iso	17c	Say	—
2SC4944	Si-N	=2SC4207:	45(2mm)	Tos	—
2SC495	Si-N	NF/S-L, 70V, 1A, 5W, 100MHz	14h	Tos	BD137, BD228, BD377, 2SD794(A), ++
2SC4954	Si-N	SMD, UHF/SHF, 9V, 10mA, 12GHz	35a	Nec	2SC5050
2SC4955	Si-N	SMD, UHF/SHF, 9V, 30mA, 12GHz	35a	Nec	2SC5050
2SC4956	Si-N	=2SC4954:	44	Nec	2SC5078
2SC4957	Si-N	=2SC4955:	44	Nec	2SC5080
2SC4956	Si-N	=2SC4954:	35a(2mm)	Nec	2SC5051
2SC4959	Si-N	=2SC4955:	35a(2mm)	Nec	2SC5051
2SC498	Si-N	=2SC495 40V	14h	Tos	BD135, BD226, BD375, 2SD794(A), ++
2SC4980	Si-N	S-L, 900/800V, 1A, 40W, <1/4µs	16j	Mat	2SC3285, 2SC3151..52, 2SC3550, ++
2SC4960A	Si-N	=2SC4960: 900/900V	18j		2SC3285, 2SC3533..34
2SC4961	Si-N	S-L, 500/400V, 5A, 35W, <700/2300ns	17c	Mat	2SC3570, 2SC4026, 2SC4073, 2SC4418, ++
2SC4962	Si-N+Di	TV/Monitor-HA, 1700V, 6A, 50W	=18c	Hit	2SC4766, 2SC4606, 2SD2253
2SC4983	Si-N+Di	TV/Monitor-HA, 1700V, 6A, 50W	=18c	Hit	BUH517D
2SC4964	Si-N	SMD, VHF/UHF, 12V, 0,1A, Ron=2Ω	35a	Hit	—
2SC4985	Si-N	=2SC4964:	35a(2mm)	Hit	—
2SC4986	Si-N	SMD, VHF/UHF, 12V, 0,1A, Ron=1,2Ω	35a	Hit	—
2SC4967	Si-N	=2SC4986:	35a(2mm)	Hit	—
2SC4966	Si-N	UHF-A, 15V, 80mA, 0,6W, 6GHz	7l	Mat	2SC3355, 2SC3605
2SC4969	Si-N	=2SC3757:	35d	Mat	→2SC3757
2SC497	Si-N	NF/S, 100V, 0,8A, 0,6W, 50MHz	2a	Tos, Mic	BC141, BC300, BCX40, 2N2102, 2N2405++
2SC4971	Si-N	=2SC4444:	35d	Mat	→2SC4444
2SC4972	Si-N	=2SC2778:	35d	Mat	→2SC2778
2SC4973	Si-N	=2SC2404:	35d	Mat	→2SC2404
2SC4974	Si-N	=2SC2480:	35d	Mat	→2SC2480
2SC4975	Si-N	=2SC3077:	35d	Mat	→2SC3077
2SC4976	Si-N	=2SC4564: 12W	30j	Say	(→2SC4564)
2SC4976	Si-N	S-L, Io-sat, 100V, 3A, 10W, 50MHz	30j	Shi	2SD1815..1616
2SC4979	Si-N	S-L, Io-sat, 100V, 5A, 10W, 50MHz	30j	Shi	—
2SC498	Si-N	=2SC497: 80V	2a		BC140..141, BC300..301, BCX40, ++
2SC4980	Si-N	S-L, Io-sat, 100V, 5A, 25W, 50MHz	15c	Shi	2SC3540, 2SC4549, 2SC4596
2SC4981	Si-N	S-L, Io-sat, 100V, 7A, 25W, 50MHz	15c	Shi	2SC3692
2SC4962	Si-N	S-L, Io-sat, 100V, 10A, 25W, 50MHz	15c	Shi	2SC3693, 2SC4595
2SC4963	Si-N	SMD, 15V, 1A, 200MHz	35	Say	—
2SC4984	Si-N	SMD, 15V, 1,5A, 200MHz	39b	Say	2SC2983, 2SC3443, 2SC4377, 2SD1621, ++
2SC4965	Si-N	S-L, 900/800V, 1A, 1,5W, <1/4µs	78b	Mat	(BUV95)
2SC4966	Si-N	S-L, 500/400V, 2A, 1,5W, <1/4µs	76b	Mat	(2SC3233, 2SC3631)
2SC4967	Si-N	SMD, S, 40V, 0,2A, 750MHz, 8/12ns	35a(1,6mm)	Say	—
2SC4966	Si-N	SMD, VHF/UHF, 15V, 0,1A, 6,5GHz	39b	Hit	—
2SC499	Si-N	Nix, 100V, 0,02A, 0,3W, 150MHz	7c	Tos	BF422, BSW32, BSS38, BSX21, ++
2SC4991	Si-N	SMD, VHF/UHF, 15V, 50mA, 9,5GHz	44u	Hit	2SC4094, 2SC4127, 2SC4592
2SC4992	Si-N	=2SC4991:	44u(2mm)	Hit	2SC4995
2SC4993	Si-N	SMD, VHF/UHF, 15V, 20mA, 10,5GHz	44u	Hit	2SC4095, 2SC5092, 2SC5097
2SC4994	Si-N	=2SC4993:	44u(2mm)	Hit	2SC4843..44, 2SC5093, 2SC5098
2SC4995	Si-N	SMD, VHF/UHF, 15V, 50mA, 11GHz	44u(2mm)	Hit	—
2SC4997	Si-N	SMD, HF/S, -/10V, 0,1A, 240MHz	35a(1,6mm)	Rhm	—
2SC4998	Si-N	=2SC4997:	35a(2mm)	Rhm	2SC4413
2SC50	Ge-N	HF/S, 20V, 0,2A, 0,1W	1a	Mat	ASY28..29, ASY73..75
2SC500	Si-N	Vid, 120V, 0,02A, 0,6W, 175MHz	2a	Tos	BF257..259, BF657..859, 2N5058..59
2SC5000	Si-N	S-L, 60V, 10A, 25W, 80MHz	17c	Tos	2SC3693, 2SC3748, 2SC4551, (2SC3255)
2SC5001(F5)	Si-N	NF-L, Io-sat, 30V, 10A 10W, 150MHz	30c	Rhm	2SC4669
2SC5002	Si-N	Display-HA, 1500/800V, 7A, 80W	18c	Sak	2SC3665A2SC3895, 2SC4757
2SC5003	Si-N+Di	=2SC5002: Int. Damper-Diode	18c	Sak	2SC3892A2SC4762, 2SC4916
2SC5004	Si-N	SMD, UHF, 20V, 0,06A, 3000MHz	35a(1,6mm)	Nec	2SC4839, 2SC5086
2SC5005	Si-N	SMD, UHF, 20V, 0,03A, 4000MHz	35a(1,6mm)	Nec	2SC4639, 2SC5086
2SC5006	Si-N	SMD, UHF, 20V, 0,1A, 3000MHz	35a(1,6mm)	Nec	—

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2SC5007	Si-N	SMD, UHF, 20V, 0,065A, 4500MHz	35a(1,6mm)	Nec	2SC4839, 2SC5086
2SC5008	Si-N	SMD, UHF, 20V, 0,035A, 5500MHz	35a(1,6mm)	Nec	2SC5108, 2SC5138
2SC5009	Si-N	SMD, UHF/SHF, 9V, 10mA, 12GHz	35a(1,6mm)	Nec	2SC5246
2SC501	Si-N	Uni, 60V, 0,3A, 0,75W, 200MHz	2a	Tos	BC140..141, BC300..302, 2N3053,++
2SC5010	Si-N	SMD, UHF/SHF, 9V, 30mA, 12GHz	35a(1,6mm)	Nec	2SC5139, 2SC5247
2SC5011	Si-N	UHF, ra, 20V, 0,1A, 6,5GHz	44u	Nec	—
2SC5012	Si-N	UHF, ra, 20V, 65mA, 9GHz	44u	Nec	—
2SC5013	Si-N	UHF, ra, 20V, 35mA, 10GHz	44u	Nec	—
2SC5014	Si-N	SHF, ra, 9V, 10mA, 12GHz	44u	Nec	—
2SC5015	Si-N	SHF, ra, 9V, 30mA, 12GHz	44u	Nec	—
2SC5016	Si-N	VHF-M, 15V, 0,05A, 1300MHz	35d	Mat	BF599, BFS20, 2SC3015, 2SC3374
2SC5018	Si-N	S, 500/400V, 0,6A, 1W, 20MHz	9c	Mat	—
2SC5019	Si-N	SMD, UHF-A, 15V, 60mA, 6GHz	39b	Mat	BFQ193, 2SC3301, 2SC3357, 2SC3607
2SC502	Si-N	HF-Tr/E, 60V, 1A, 0,6W, >150MHz	2a	Tos	BFS22, BFS51, BFQ42, 2N4427, ++
2SC5020	Si-N	SMD, AM/FM/TV-ZF, 30V, 15mA, 650MHz	35a(2mm)	Mat	2SC3931
2SC5021	Si-N	=2SC5020:	35a(1,6mm)	Mat	2SC4627, 2SC4655, 2SC4915
2SC5022	Si-N	S-L, 1500/1500V, 20mA, B>10	17c	Hit	2SC4633, 2SC4635
2SC5023	Si-N	=2SC4706: Iso, 8W, 1GHz	14b	Hit	2SC3953, (2SC3598..99)
2SC5024	Si-N	=2SC4704: Iso, 6W	14b	Hit	2SC3956, (2SC3601, 2SC4704)
2SC5025	Si-N	=2SC3652: Iso	14b	Hit	—
2SC5026	Si-N	SMD, lo-sat, 60V, 1A, 120MHz	39b	Mat	2SC4409, 2SD1615A
2SC5027	Si-N	S, CTV-HA-Tr, 300/300V, 0,1A, 70MHz	12b	Tos	2SC3271, 2SC3789..90, 2SC4826
2SC5026	Si-N	Uni, lo-sat, 60V, 2A, 1,3W, 100MHz	12b	Tos	(2SD1682)
2SC5029	Si-N	Uni, 50V, 3A, 1,3W, 100MHz	12b	Tos	(2SC3420)
2SC503(D,M)	Si-N	Uni, 100V, 0,6A, 0,6W, 60MHz	2a	Tos, Mic	BC141, BC300, BCX40, BSW39, ++
2SC5030	Si-N	hi-beta, lo-sat, 50V, 5A, 1,3W, 150MHz	12b	Tos	—
2SC5032	Si-N	S-L, 500/400V, 3A, 30W, <1/3,3µs	17c	Mat	2SC4052, 2SC4160, 2SC4421, 2SC4533, ++
2SC5034	Si-N	S-L, 500/400V, 7A, 35W, <1/2,3µs	17c	Mat	BU308F, 2SC3571, 2SC4130, 2SC4559, ++
2SC5035	Si-N	S-L, 800/500V, 5A, 40W, <1,5/4µs	17c	Mat	BUT11(A)F, 2SC3353, 2SC3750, 2SC3795(A)
2SC5036	Si-N	S-L, 900/800V, 1A, 30W, <700/2800ns	17c	Mat	BUX65F, 2SC3794A, 2SC3976(A)
2SC5036A	Si-N	=2SC5036: 1000/800V	17c		BUX85F, 2SC3751, 2SC3976(A), 2SC4231
2SC5037	Si-N	S-L, 900/800V, 3A, 40W, <700/2800ns	17c	Mat	2SC3752, 2SC3979(A), 2SC4304, 2SC4517(A)
2SC5037A	Si-N	=2SC5037: 1000/800V	17c		2SC3752, 2SC3979A, 2SC4234, 2SC4517A
2SC5039	Si-N	hi-beta, lo-sat, 30V, 2A, 0,9W, B>1200	7c(9mm)	Tos	2SC3225, 2SC4399
2SC504	Si-N	=2SC503: 60V	2a	Tos, Mic	BC140..141, BC300..301, BSW39, ++
2SC5041	Si-N+Di	=2SC5042 int. Damper-Diode	18c	Say	BUH517D, 2SC4983
2SC5042	Si-N	CRT HA, hi-res, 1800/600V, 7A, 60W	16c	Say	BUH417, BUH517, 2SC4797
2SC5043	Si-N+Di	=2SC5044: int. Damper-Diode	18c	Say	BUH517D
2SC5044	Si-N	CRT HA, hi-res, 1800/800V, 10A, 70W	18c	Say	2SC4879
2SC5045	Si-N	CRT HA, hi-res, 1800/800V, 15A, 75W	18c	Say	—
2SC5046	Si-N	CRT HA, hi-res, 1800/800V, 15A, 180W	77j	Say	—
2SC5047	Si-N	CRT HA, hi-res, 1800/800V, 25A, 250W	77j	Say	—
2SC5048	Si-N	Display HA, hi-res, 1500/600V, 12A, 50W	18c	Tos	BU2525AF, BU2527AF
2SC5049	Si-N	SMD, VHF/UHF, 15V, 20mA, 10GHz	35a	Hit	BFR505, 2SC3585, 2SC5094
2SC505	Si-N	Vid, 300/300V, 0,2A, 0,6W, 60MHz	2a	Tos, Mic	BF259, BF659, BFR59, BFS89, 2N5056
2SC5050	Si-N	SMD, VHF/UHF, 15V, 50mA, 11GHz	35a	Hit	—
2SC5051	Si-N	=2SC5050:	35a(2mm)	Hit	—
2SC5052	Si-N	Uni, 120V, 0,6A, 1W, 120MHz	9c	Tos	2SC2235, 2SC2383, 2SC3332, 2SC4612, ++
2SC5053	Si-N	SMD, lo-sat, 60V, 1A, 150MHz	39b	Rhm	2SC3444, 2SD1615, 2SD1622..23
2SC5057	Si-N	TV/Monitor-HA, 1700/900V, 20A, 200W	77j	Hit	—
2SC5056	Si-N	TV/Monitor-HA, 1700/900V, 12A, 150W	77j	Hit	2SC4880, 2SC4698
2SC508	Si-N	=2SC505: 200/200V	2a	Tos, Mic	BF256..259, BFR58..59, 2N5056..59
2SC5060	Si-N-Darl+Di	+Z-Di(B→C), 90V, 1A, 1W, 60MHz, B>1k	9c(H)	Rhm	—
2SC5061	Si-N	NF-Tr, -/60V, 0,7A, 0,9W	7c(9mm)	Rhm	2SC2383, 2SC3226, 2SD1292, 2SD1612
2SC5062	Si-N	lo-sat, -/20V, 3A, 0,9W	7c(9mm)	Rhm	2SC4761, 2SD1347
2SC5063	Si-N	S-L, 500/400V, 1,5A, 25W, <700/2300ns	30j	Mat	2SC3403, 2SC4754
2SC5064	Si-N	SMD, VHF/UHF, 20V, 30mA, 7GHz	35a	Tos	BFQ67, BFR182..183, 2SC3585
2SC5065	Si-N	=2SC5064:	35a(2mm)	Tos	BFQ67W, BFR182W..183W, 2SC5190
2SC5066	Si-N	=2SC5064:	35a(1,6mm)	Tos	2SC4840, 2SC5108
2SC5067	Si-N	TV/Monitor-HA, 1500/800V, 6A, 50W	≈18c	Hit	BU2508AF, 2SC3896A, 2SC4757, 2SD2372, +
2SC5068	Si-N	TV/Monitor-HA, 1500/600V, 10A, 50W	≈18c	Hit	BU2520AF, 2SC4199A, 2SC4542, 2SC4759
2SC5066A	Si-N	≈2SC5086: 12A	≈18c		BU2525AF, 2SC4692, 2SC5105
2SC5069	Si-N	≈2SC8607: SMD	39b	Say	—
2SC507	Si-N	Nix, Vid, 170V, 0,1A, 0,75W, 250MHz	2a	Tos, Mic	BF257..259, BF657..659, 2N5058..59
2SC5070	Si-N	≈2SC5069:	≈12b	Say	—
2SC5071	Si-N	S-L, 500/400V, 12A, 100W, 10MHz	18c	Sak	2SC4297, 2SC4423, (BUW13(A), BUV48)

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2SC5072	Si-N	=2SC4911K:	35a(1,6mm)	Rhm	2SC4987
2SC5073	Si-N	=2SC4699K:	35a(1,6mm)	Rhm	2SC4987
2SC5075	Si-N	S-Reg, 500/400V, 2A, 1,3W, <1/3,5µs	12b	Tos	(2SC4917)
2SC5076	Si-N	Uni, lo-sat, 60V, 5A, 1,3W, 120MHz	12b	Tos	(2SD1903)
2SC5077	Si-N	S-L, 800/500V, 7A, 45W, <1/3,3µs	17c	Mat	BU307F, BUT12AF, BUT22BF, CF
2SC5078	Si-N	SMD, VHF/UHF, 15V, 20mA, 12GHz	44u	Hit	—
2SC5079	Si-N	=2SC5078:	44u(2mm)	Hit	2SC4995
2SC508	Si-N	AMP, 375/350V, 7A, 45W, 25MHz	23a	Tos	BU408..408, 2SD823, 2SD1136, 2SD1159, ++
2SC5080	Si-N	SMD, VHF/UHF, 15V, 50mA, 13,5GHz	44u	Hit	—
2SC5081	Si-N	=2SC5080:	44u(2mm)	Hit	—
2SC5082M	Si-N	TV-ZF, -/25V, 50mA, 650MHz	9c	Rhm	BF920, BF921S, BF959
2SC5083	Si-N	=2SC5082M: Pins 14mm	9c	Rhm	→2SC5082M
2SC5084	Si-N	SMD, VHF/UHF, 20V, 80mA, 7GHz	35a	Tos	BFR193, BFR520, 2SC3356, 2SC3445
2SC5085	Si-N	=2SC5084:	35a(2mm)	Tos	BFS520, BFS540
2SC5086	Si-N	=2SC5084:	35a(1,6mm)	Tos	—
2SC5087	Si-N	SMD, VHF/UHF, 20V, 80mA, 7GHz	44u	Tos	—
2SC5088	Si-N	=2SC5087:	44u(2mm)	Tos	—
2SC5089	Si-N	SMD, VHF/UHF, 20V, 40mA, 10GHz	35a	Tos	2SC3583, 2SC3585, 2SC3904, 2SC4591
2SC509(G)	Si-N	Uni, 35V, 0,5A, 0,6W, 100MHz	9b	Tos	BC337, BC635, BC637, 2SC3377, ++
2SC5090	Si-N	=2SC5089:	35a(2mm)	Tos	2SC4593, 2SC5190
2SC5091	Si-N	=2SC5089:	35a(1,6mm)	Tos	—
2SC5092	Si-N	SMD, VHF/UHF, 20V, 40mA, 10GHz	44u	Tos	2SC4094..95, 2SC4127
2SC5093	Si-N	=2SC5092:	44u(2mm)	Tos	2SC4843
2SC5094	Si-N	SMD, VHF/UHF, 20V, 15mA, 10GHz	35a	Tos	BFR505, 2SC3585, 2SC5089
2SC5095	Si-N	=2SC5094:	35a(2mm)	Tos	BFS505, 2SC5090, 2SC5190
2SC5096	Si-N	=2SC5094:	35a(1,6mm)	Tos	2SC4840..41, 2SC5091
2SC5097	Si-N	SMD, VHF/UHF, 20V, 15mA, 10GHz	44u	Tos	2SC4095, 2SC5092
2SC5098	Si-N	=2SC5097:	44u(2mm)	Tos	2SC4843, 2SC5093
2SC5099	Si-N	NF/S-L, 120V, 6A, 60W, 20MHz	18c	Sak	2SC3385, 2SC4689, 2SD2064, (BD245C..F)
2SC509GT	Si-N	=2SC509: 0,8W	7c		BC337, BC635, BC637, 2SC3377, ++
2SC51	Si-N	HF-Tr/E, 60V, 0,3A, 1W, 160MHz	2a	Fui	BFX55, 2N2218..19, 2N3299..3300, ++
2SC510(M)	Si-N	HF/NF/S, 140/100V, 1,5A, 0,8W, 60MHz	2a	Tos	BSS43, BSW68, 2SC1860
2SC5100	Si-N	NF/S-L, 160V, 6A, 75W, 20MHz	18c	Sak	2SC4386, (BD245D..F)
2SC5101	Si-N	NF/S-L, 200V, 10A, 80W, 20MHz	18c	Sak	2SC4387, (BD245F)
2SC5103	Si-N	S-L, lo-sat, 100V, 5A, 10W, 120MHz	30j	Rhm	2SC3303
2SC5104	Si-N	S-L, 500/400V, 3A, 30W, <1/3,3µs	17c	Mat	BUT11(A)F, 2SC3570, 2SC4052, 2SC4160, ++
2SC5105	Si-N	Monitor-HA, 1500/800V, 12A, 50W	≈18c	Hit	BU2525AF, 2SC4692
2SC5106	Si-N	SMD, VHF/UHF, 20V, 30mA, 6GHz	35a	Tos	BFR182, 2SC3011, 2SC5064
2SC5107	Si-N	=2SC5106:	35a(2mm)	Tos	BFR182W, 2SC5065
2SC5108	Si-N	=2SC5106:	35a(1,6mm)	Tos	2SC5066
2SC5109	Si-N	SMD, VHF/UHF, 20V, 60mA, 5GHz	35a	Tos	BF770, BFQ67, BFR163, 2SC3513, 2SC3704
2SC511	Si-N	=2SC510: 120/80V	2a	Tos	BSS42..43, BSW67..68, BSX47, BSV84++
2SC5110	Si-N	=2SC5109:	35a(2mm)	Tos	BFQ67W, BFR183W, 2SC3937
2SC5111	Si-N	=2SC5109:	35a(1,6mm)	Tos	—
2SC5112	Si-N	S-L, -/500, 5A, 40W	17j	Rhm	BUT11, BUT18, BUV46, 2SC3047, ++
2SC5113	Si-N	=2SC5112: Iso, 35W	17c	Rhm	BUT11F, BUT18F, BUV46FI, 2SC3750, ++
2SC5114	Si-N	S-L, -/500, 5A, 80W	18c	Rhm	BUW11F, 2SC4300, 2SC4427, 2SC4457, ++
2SC5115	Si-N	S-L, -/500, 5A, 35W	30j	Rhm	2SC4172, 2SC4222, 2SC4600, (BUT11, ++)
2SC5116	Si-N	S-L, -/550, 4A, 40W	17j	Rhm	BUT11, BUT18, BUV46, 2SC3491, ++
2SC5117	Si-N	=2SC5116: Iso, 35W	17c	Rhm	BUT11F, BUT18F, BUV46FI, 2SC3750, ++
2SC5118	Si-N	=2SC5118: Iso, 80W	18c	Rhm	BUW11F, 2SC4300, 2SC4427, 2SC4457, ++
2SC5119	Si-N	S-L, -/550, 4A, 35W	30j	Rhm	2SC4172, 2SC4222, 2SC4600, (BUT11, ++)
2SC512(M)	Si-N	=2SC510: 100/60V	2a	Tos	BCX40, BSW67..68, BSX46..47, ++
2SC5120	Si-N	Vid-E, 150/150V, 0,2A, 8W, 500MHz	14b	Hit	2SC3787, 2SC3956
2SC5121	Si-N	Vid, 400/400V, 0,07A, >50MHz	14b	Mat	(BF850, 2SC3418)
2SC5122	Si-N	S-Reg, 400/400V, 0,05A, 0,9W	7c(9mm)	Tos	2SC2267, 2SC3469, 2SC4166, 2SD1385
2SC5124	Si-N	HA, 1500/800V, 10A, 100W	18c	Sak	BU2520AF, 2SC4589, 2SC4759, 2SD2373, ++
2SC5127	Si-N	S-L, 800/500V, 1,5A, 25W, <1/3,3µs	17c	Mat	BUX84F..85F, 2SC3352, 2SC3794(A), ++
2SC5127A	Si-N	=2SC5127: 900/500V	17c		BUX85F, 2SC3794(A), 2SC3978(A)
2SC5128	Si-N	S-L, 800/500V, 5A, 40W, <1/3,3µs	17c	Mat	BUT11(A)F, 2SC3353, 2SC3750, 2SC3795, ++
2SC5129	Si-N	Display-HA, hi-res, 1500/600V, 10A, 50W	18c	Tos	BU2520AF, BUH715, 2SC4542
2SC5129	Si-N				—
2SC513	Si-N	=2SC510: 70/40V	2a	Tos	BCX40, BSW65..68, BSX45..47, ++
2SC5130	Si-N	S-Reg, 600/400V, 5A, 30W, 20MHz	17c	Sak	BUT11(A)F, 2SC3750, 2SC3795, 2SC4054, ++
2SC5132	Si-N+Di	=2SC5133: Iso	≈18c	Hit	2SC4764, 2SD1556, 2SD2095, 2SD2370, ++
2SC5132A	Si-N+Di	=2SC5133: Iso, 6A	≈18c	Hit	BU2508DF, 2SC4783, 2SD2371

2SC5133	Si-N+Di	Monitor-HA, 1500V, 6A, 50W	18j	Hit	BU2508D, 2SC3482, 2SC4292
2SC5136	Si-N	iSMD, VHF/UHF, 25V, 50mA, 3,8GHz	35a(1,6mm)	Hit	—
2SC5137	Si-N	SMD, VHF/UHF, 15V, 20mA, 10GHz	35a(1,6mm)	Hit	2SC4841, 2SC5096
2SC5136	Si-N	SMD, VHF/UHF, 20V, 30mA, 6GHz	36a(1,6mm)	Hit	2SC5066, 2SC5108
2SC5139	Si-N	SMD, VHF/UHF, 15V, 50mA, 11GHz	35a(1,6mm)	Hit	—
2SC514	Si-N	NF/S/Vid-L, 300/300V, 0,1A, 4W, 20MHz	≈22	Tos	2SC1505..1507, 2SC1755..1757, 2SC1905
2SC5140	Si-N	SMD, VHF/UHF, 15V, 20mA, 9GHz	35a(1,6mm)	Hit	2SC4841, 2SC5096
2SC5141	Si-N	SMD, VHF/UHF, 20V, 50mA, 5,8GHz	35a(1,6mm)	Hit	—
2SC5142	Si-N	Display-HA, 1500/600V, 20A, 200W	77j	Tos	2SC3994, 2SC4290(A), 2SC4897
2SC5143	Si-N+Di	Display-HA, hi-res, 1700/700V, 10A, 50W	18c	Tos	—
2SC5144	Si-N	Display-HA, hi-res, 1700/600V, 20A, 200W	77j	Tos	2SC5057
2SC5145	Si-N	S-L, 800/500V, 5A, 40W, <1/4µs	30c	Mat	2SC4172, 2SC4222, 2SC4600, (BUT 11(A)++)
2SC5147	Si-N	Vid, 300/300V, 0,1A, 10W, 100MHz	17c	Rhm	2SC3565, 2SC3942, 2SC3945, 2SC4075
2SC5148	Si-N	Display-HA, hi-res, 1500/600V, 6A, 50W	18c	Tos	BU2525AF, 2SC3896, 2SC4758
2SC5149	Si-N+Di	=2SC5148: int. Damper-Diode	18c	Tos	BU2520DF, 2SC3693A, 2SC4763
2SC515(A)	Si-N	NF/S/Vid-L, 300/300V, 0,1 (A=0,15)A, 6W	22a	Tos	2SC1505..1507, 2SC1755..1757, 2SC1905
2SC5150	Si-N	Display-HA, hi-res, 1700/700V, 10A, 50W	18c	Tos	—
2SC5154	Si-N	Uni, 160/160V, 1,5A, 1,3W, 100MHz	12b	Tos	(2SC3117, 2SD669, 2SD1563A)
2SC5155	Si-N	hi-beta, 50V, 3A, 20W, 260MHz, B>800	30j	Say	2SD1584, 2SD1754(A)
2SC5158	Si-N	S-L, 1000/800V, 3A, 70W, <1/3µs	18c	Mat	BUW11AF, 2SC4426, 2SC4583
2SC5158	Si-N	S-L, 500/400V, 10A, 70W, <700/2300ns	18c	Mat	2SC4296, (BUV47(A..C), BUW12(A),++)
2SC5159	Si-N	S-L, 900/800V, 3A, 70W, <700/2800ns	18c	Mat	BUW11AF, 2SC4299, 2SC4445
2SC516	Si-N	Uni, 100/60V, 1,5A, 0,8W, 50MHz	2a	Tos	BCX40, BSW66..66, BSX48..47,++
2SC5160	Si-N	S-L, 500/400V, 7A, 70W, <700/2300ns	18c	Mat	2SC4296, (BUP22(A..C), BUW12(A),++)
2SC5161(F5)	Si-N	S-L, -/400V, 2A, 10W	30j	Rhm	—
2SC5162(F5)	Si-N	S-L, -/600V, 1A, 10W	30j	Rhm	2SC3363
2SC516A	Si-N	=2SC516: 140/100V	2a	Tos	BSS43, BSW66, 2SC1860
2SC517	Si-N	HF/S-L, 60V, 2A, PQ>4W(50MHz)	43m	Tos	—
2SC5171	Si-N	TV, L, 180/180V, 2A, 20W, 200MHz	17c	Tos	2SC3298A, 2SC4159, 2SC4883A
2SC5172	Si-N	S-Reg, 800/400V, 5A, 25W, <700/3000ns	17c	Tos	BUT11(A)F, 2SC3750, 2SC3795, 2SC4054,++
2SC5173	Si-N	Vid, S-L, 300/300V, 0,1A, 70MHz	15c	Tos	2SC3585, 2SC3942, 2SC3945, 2SC4075
2SC5174	Si-N	Uni, 230/230V, 1A, 1,8W, 100MHz	15c	Tos	2SC4793
2SC5175	Si-N	Uni, lo-sat, 60V, 5A, 1,8W, 100MHz	15c	Tos	2SC3540, 2SC3746..47, 2SC3691
2SC5176	Si-N	Uni, lo-sat, 100V, 5A, 1,8W, 120MHz	15c	Tos	2SC3540, 2SC3691, 2SC4549, 2SC4596
2SC5177	Si-N	SMD, SHF, 5V, 10mA, 10GHz	35a	Nec	BFR505, 2SC5049, 2SC5094
2SC5178(R)	Si-N	SMD, SHF, 5V, 10mA, 10,5GHz	44	Nec	2SC4993, 2SC5078, 2SC5097
2SC5179	Si-N	SMD, SHF, 5V, 10mA, 10GHz	36a(2mm)	Nec	BFS505, 2SC4899, 2SC5095
2SC518	Si-N	AMP, 140V, 5A, 50W	23a	Tos	BU104, BU606..606, 2SD916, 2SD1154
2SC5180	Si-N	SMD, SHF, 5V, 10mA, 12GHz	44(2mm)	Nec	2SC4844, 2SC4994, 2SC5096
2SC5181	Si-N	SMD, SHF, 5V, 10mA, 10GHz	35a(1,6mm)	Nec	2SC4841, 2SC5096, 2SC5137, 2SC5140
2SC5182	Si-N	SMD, SHF, 5V, 30mA, 9GHz	35a	Nec	2SC35?5, 2SC5089
2SC5183(R)	Si-N	SMD, SHF, 5V, 30mA, 9,5GHz	44	Nec	2SC4095, 2SC5092
2SC5184	Si-N	SMD, SHF, 5V, 30mA, 9GHz	35a(2mm)	Nec	2SC5090, 2SC5190
2SC5185	Si-N	SMD, SHF, 5V, 30mA, 10GHz	44(2mm)	Nec	2SC4843, 2SC5093
2SC5186	Si-N	SMD, SHF, 5V, 30mA, 9GHz	35a(1,6mm)	Nec	2SC4840, 2SC5091
2SC5187	Si-N	SMD, S, 25V, 1,5A, 50/160ns	39b	Say	2SC2982, 2SC4377, 2SD1821, 2SD1766,++
2SC5188	Si-N	SMD, S, 25V, 3A, 50/120ns	39b	Say	2SD1119, 2SD1620, 2SD2150
2SC5189	Si-N	SMD, S, 25V, 5A, 50/160ns	39b	Say	2SD1963, 2SD2540
2SC518A	Si-N	=2SC518: 160V	23a		BU104, BU606..606, 2SD916, 2SD1154
2SC519	Si-N	NF/S-L, 110/100V, 7A, 50W, 10MHz	23a	Tos	BD245C, BD550, 2N4348, 2SD1046,++
2SC5190	Si-N	SMD, SHF/UHF-A, 9V, 30mA, 10GHz	35a(2mm)	Mat	2SC4593, 2SC4805
2SC5191	Si-N	SMD, UHF, 9V, 0,1A, 4000MHz	35a	Nec	2SC3356
2SC5192(R)	Si-N	SMD, UHF, 9V, 0,1A, 4000MHz	44	Nec	—
2SC5193	Si-N	SMD, UHF, 9V, 0,1A, 4000MHz	35a(2mm)	Nec	—
2SC5194	Si-N	SMD, UHF, 9V, 0,1A, 4000MHz	44(2mm)	Nec	—
2SC5195	Si-N	SMD, UHF, 9V, 0,1A, 4500MHz	44(2mm)	Nec	—
2SC5196	Si-N	NF-HiFi-E, 80/80V, 6A, 60W, 30MHz	18j	Tos	BD245C, BDV93, 2SC3258, 2SD895,++
2SC5197	Si-N	NF-HiFi-E, 120/120V, 6A, 80W, 30MHz	18j	Tos	BD245C, BD545D, 2SC3181, 2SD718,++
2SC5196	Si-N	NF-HiFi-E, 140/140V, 10A, 100W, 30MHz	18j	Tos	BD245D, 2SC2837, 2SC2706, 2SC3182,++
2SC5199	Si-N	NF-HiFi-E, 160/160V, 12A, 120W, 30MHz	77j	Tos	2SC3281, 2SD1975, 2SD2155
2SC519A(A-M)	Si-N	=2SC519: 130/110V, 0,4/4,9µs	23a		BD245D, 2N4348, 2SC2708, 2SD1048,++-
2SC52	Si-N	HF-Tr, 40V, 0,1A, 0,5W, 350MHz	2a	Fui	BFW16..17, BFX55
2SC520(A,A-M)	Si-N	=2SC519..: 100/80V	23a	Tos	BD245C, BDV95, BDX95, 2SD718,++
2SC5200	Si-N	NF-HiFi-E, 230/230V, 15A, 150W, 30MHz	77j	Tos	2SC4029
2SC5201	Si-N	S, 600/600V, 0,05A, 0,9W, 30MHz	7c(9mm)	Tos	2SD1573
2SC5208	Si-N	S-L, 500/400V, 5A, 25W, tf=600ns	17c	Hit	2SC3570, 2SC4026, 2SC4073, 2SC4418,++

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2SC5207A	Si-N	Display-HA, 1500/800V, 10A, 50W	~18c	Hit	BU2520AF, BUH715, 2SC5129
2SC5209	Si-N	SMD, hi-beta, 50V, 1A, 130MHz, B>600	39b	Mit	2SC3727
2SC521(A)	Si-N	=2SC519: 70V	23a	Tos	BD245A, BDV93, BDX93, 2SD895, ++
2SC5210	Si-N	SMD, Vid, 300/300V, 0,1A, 80MHz	39b	Mit	BFN18, 2SC3380, 2SC3515, 2SC3554, 2SC4189
2SC5211	Si-N	SMD, Uni, 55V, 0,4A, 150MHz	39b	Mit	BCX55, 2SC3444, 2SD1006, 2SD1767, ++
2SC5212	Si-N	SMD, Uni, 25V, 0,7A, 180MHz	39b	Mit	BCX54, 2SC3444, 2SC4376, 2SC4539, ++
2SC5213	Si-N	SMD, Uni, 120/120V, 0,1A, 200MHz	39b	Mit	—
2SC5214	Si-N	SMD, Uni, 30V, 1A, 100MHz	39b	Mit	BCX54..56, 2SC3444, 2SD1005, 2SD1615, ++
2SC5216	Si-N	SMD, VHF/UHF, 15V, 50mA, 9GHz	35a	Hit	2SC3583, 2SC3904, 2SC4591
2SC5219	Si-N+Di	Display-HA, 1700/-V, 8A, 50W	~18c	Hit	BUH517D, 2SC5143
2SC522(M)	Si-N	HF/S-L, 140/100V, 1,5A, 10W, 80MHz	43m	Tos	(2SC3117, 2SD669)
2SC5221	Si-N	S-L, 490/490V, 0,2A, 10W, B>150	30j	Mat	—
2SC5222	Si-N	S-L, 500/500V, 0,5A, 10W, B>100	30j	Mat	—
2SC5223	Si-N	S-L, 500/500V, 1A, 10W, B>100	30j	Mat	—
2SC5224	Si-N	S-L, 500/500V, 2A, 10W, B>100	30j	Mat	—
2SC5225	Si-N	Vid, 100V, 0,3A, 0,625W, 1,4GHz	7e	Hit	—
2SC5226	Si-N	SMD, VHF/UHF, 20V, 70mA, 7GHz	35a(2mm)	Say	BFS520, 2SC5085
2SC5227	Si-N	=2SC5226:	35a	Say	BFR193, BFR520, 2SC3445, 2SC5084
2SC5228	Si-N	=2SC5226:	44u	Say	2SC5087
2SC5229	Si-N	=2SC5230: SMD	39b	Say	BFQ193, 2SC3301, 2SC3607
2SC523	Si-N	=2SC522: 120/80V	43m	Tos	(2SC3117, 2SD669)
2SC5230	Si-N	VHF/UHF, 20V, 70mA, 0,4W, 6,5GHz	7f	Say	2SC3355, 2SC3507
2SC5231	Si-N	SMD, VHF/UHF, 20V, 70mA, 7GHz	35a(1,6mm)	Say	2SC5139
2SC5237	Si-N	Vid-E, 250/250V, 0,15A, 6W, 400MHz	~14b	Hit	2SC4623
2SC5238	Si-N	Monitor-HA, 1500/800V, 50A, 160W	17j	Say	—
2SC5239	Si-N	S-L, S-Reg, 900/550V, 3A, 50W, 6MHz	17j	Sak	BUT11A, BUV46A, 2SC3146, 2SC3150
2SC524(M)	Si-N	=2SC522: 100/60V	43m	Tos	(BD139, BD230, BD379, 2SD1177..1178)
2SC5242	Si-N	=2SC5200: 130W	18j	Tos	2SC3263
2SC5243	Si-N	Monitor-HA, 1700V, 15A, 200W	77j	Mat	2SC4896
2SC5244	Si-N	Monitor-HA, 1500V, 30A, 200W	77j	Mat	—
2SC5244A	Si-N	=2SC5244: 1600	77j		—
2SC5245	Si-N	SMD, VHF/UHF, 20V, 30mA, 11GHz	35a(2mm)	Say	—
2SC5246	Si-N	SMD, VHF/UHF, 15V, 20mA, 12GHz	35a(1,6mm)	Hit	2SC5139
2SC5247	Si-N	SMD, VHF/UHF, 15V, 50mA, 13,5GHz	35a(1,6mm)	Hit	2SC5139
2SC5249	Si-N	S-L, S-Reg, 600/600V, 3A, 35W, 6MHz	17c	Sak	BUT11(A)F, 2SC4054, 2SC4304, 2SD1571, ++
2SC525	Si-N	=2SC522: 70/40V	43m	Tos	(BD139, BD230, BD377, 2SD1177..1178)
2SC5250	Si-N+Di	Display-HA, 1500/-V, 6A, 50W	~18c	Hit	BU2520DF, 2SC4763
2SC5251	Si-N	Display-HA, 1500/800, 12A, 50W	~18c	Hit	BU2525AF, 2SC4890, 2SC5048
2SC5252	Si-N	Display-HA, 1500/800, 15A, 50W	~18c	Hit	2SC4891
2SC526(M)	Si-N	Vid, 165V, 55mA, 0,75W, 250MHz	2a	Mat,	BF257..259, BF657..659, 2N5058..59
2SC5264	Si-N	HA, S-L, 1000/450V, 5A, 30W	17c	Say	—
2SC5265	Si-N	HA, S-L, 1200/600V, 4A, 30W	17c	Say	—
2SC5266	Si-N	S-L, 600/400V, 5A, <700/3000ns	15c	Tos	BUT11(A)F, 2SC3750, 2SC3795, 2SC4056, ++
2SC527	Si-N	HF, 35V, 10mA, 0,13W, 340MHz	5g	Mat	BF196..199, BF224..225, BF505, ++
2SC5271	Si-N	S-L, S-Reg, 300/200V, 5A, 30W, 10MHz	17c	Sak	2SC3570, 2SC3573, 2SC4073, 2SC4129, ++
2SC5273	Si-N	S-L, Focus, 1300/1300V, 0,03A, 1,6A	17j	Hit	2SC3875
2SC5275	Si-N	SMD, VHF/UHF, 20V, 30mA, 11GHz	35a(2mm)	Say	2SC5051
2SC5276	Si-N	=2SC5275:	35a(3mm)	Say	2SC5050
2SC5277	Si-N	=2SC5275:	35a(1,6mm)	Say	2SC5139
2SC5279	Si-N	S-L, 600/400V, 2A, <1/3,5µs	15c	Tos	BUT11(A)F, 2SC4052, 2SC4304, 2SD1571, ++
2SC528	Si-N	Uni, 20V, 0,15A, 0,2W, 100MHz	9b	Hit	SC168, SC163, SC238, BC548, 2SD767++
2SC5287	Si-N	S-L, S-Reg, 900/550V, 5A, 80W, 6MHz	18j	Sak	BUW11A, BUW131A, 2SC3636, 2SC3642
2SC5289	Si-N	SMD, UHF/SHF, 9V, 0,15A	44	Nec	—
2SC5289	Si-N	SMD, UHF/SHF, 9V, 0,3A	44	Nec	—
2SC529	Si-N	HF, 30V, 0,1A, 0,1W, 230MHz	9b	Hit	BC163, BC238, BC548, BF254..255, ++
2SC5291	Si-N	=2SC3902: 1,5W	~12b	Say	(→2SC3902)
2SC5296	Si-N+Di	=2SC5297: int. Damper-Diode	18c	Say	BU2508DF, 2SC4124, 2SC4763
2SC5297	Si-N	Monitor-HA, 1500/600, 6A, 60W	18c	Say	BU2508AF, 2SC3896, 2SC4756
2SC5298	Si-N+Di	=2SC5299: int. Damper-Diode	18c	Say	BU2520DF, 2SC4125, 2SC4878
2SC5299	Si-N	Monitor-HA, 1500/600, 10A, 70W	18c	Say	BU2520AF, BUH715, 2SC4599
2SC53	Si-N	HF-Tr, 25V, 0,1A, 0,6W, 300MHz	2a	Fui	BFW16..17, BFX55
2SC530	Si-N	HF, 30V, 0,1A, 0,1W, 230MHz	9b	Hit	BC163, BC238, BC548, BF254..255, ++
2SC5307	Si-N	SMD, S, 400/400V, 0,05A	39b	Tos	2SC4546, 2SD2413
2SC531	Si-N	HF, 30V, 0,1A, 0,1W, 230MHz	9b	Hit	BC163, BC238, BC548, BF254..255, ++
2SC5319	Si-N	SMD, SHF, 8V, 20mA, 13GHz	44(2mm)	Tos	—
2SC532	Si-N	FM-ZF, 30V, 0,1A, 0,1W, 230MHz	9b	Hit	BF240..241, BF254..255, BF594..595, ++

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2SC5327	Si-N	Uni, 40V, 0,5A, 0,5W, 300MHz	7		BC337, BC635, 2SD863, 2SD1225..26,++
2SC5328	Si-N	Uni, 60V, 0,15A, 0,4W, >80MHz	7		BC174, BC182, BC546, 2SD767,++
2SC5329	Si-N	Uni, 35V, 0,6A, 0,625W, 130MHz	7		BC337, BC635, 2SD863, 2SD1225..26,++
2SC533	Si-N	FM-ZF, 230MHz	9b	Hit	BF240..241, BF254..255, BF594..595,++
2SC5330	Si-N	HF, 30V, 0,02A, 0,4W, >300MHz	7		BF198, BF225, BF310, BF367, BF596++
2SC5331	Si-N	HA, 1500/600V, 15A, 160W	77j	Tos	2SC3996, 2SC4269A
2SC5332	Si-N	HA, 1700/800V, 10A, 200W	77j	Tos	2SC4532, 2SC4880
2SC5333	Si-N	S-L, S-Reg, 300/300V, 2A, 35W, 10MHz	17c	Sak	2SC3309, 2SC3560..61, 2SC3868, 2SC3969
2SC5339	Si-N	HA, 1500/600V, 8A, 50W	18c	Tos	BU2520AF, 2SC3886A, 2SC38896A, 2SC4758+
2SC534	Si-N	FM-V/M/O, 30V, 0,1A, 0,1W, 230MHz	9b	Hit	BF240, BF255, BF495, BF595,++
2SC535	Si-N	FM/VHF-VM/O, 700MHz	9b,7c	Hit	BF225, BF310, BF314, BF502, BF505++
2SC536(..P..)	Si-N	Uni, 40..55V, 0,1A, 0,2W, 180MHz	≈7c,7c	Say, Mic	BC183, BC237, BC547, BF254255,++
2SC537(FP)	Si-N	=2SC536: 20V	≈7c,7c	Say, Mic	BC163, BC238, BC548, BF254255,++
2SC538(Z)	Si-N	Uni, 25V, 0,05A, 0,3W, 150MHz	2a	Mat, Mic	BC168, BC183, BC236, BC546, 2SC1890+
2SC538A(AZ)	Si-N	=2SC538: 45V	2a		BC167, BC162, BC237, BC547, 2SC1890+
2SC539(Z)	Si-N	=2SC538: ra	2a	Mat	BC169, BC184, BC239, BC549, 2SC2675+
2SC54	Si-N	=2SC52: 0,3W	2a		BFX59, (BFW16..17, BFX55)
2SC540	Si-N	Min, Uni, Ra, 30V, 0,1A, 0,15W, 100MHz	24b	Nec	(BC169, BC184, BC239, BC549, 2SC2675,++)
2SC541	Si-N	VHF-A/Tr, 50V, 1A, PQ=4W(175MHz)	2a	Fui	BFS23
2SC542	Si-N	VHF-L, 65V, 1,5A, PQ=6W(175MHz)	49a	Fui	BLY60, 2N3632
2SC543	Si-N	VHF-L, 65V, 3A, PQ=14,5W(175MHz)	49a	Fui	BLY35, 2N3632
2SC544	Si-N	HF/ZF, 40V, 0,03A, 0,15W, 350MHz	≈7c	Say	BF198..199, BF224..225, BF505,++
2SC545	Si-N	HF/ZF, 20V, 0,03A, 0,15W, 350MHz	≈7c	Say	BF198..199, BF224..225, BF505,++
2SC546	Si-N	HF/ZF, 30V, 0,03A, 0,15W, 600MHz	≈7c	Say	BF198..199, BF224..225, BF505,++
2SC547(D)	Si-N	VHF-A/Tr, 65V, 1A, PQ>2,5W(175MHz)	2a	Tos	BFS23, BLY34
2SC548	Si-N	VHF-A/Tr, 36V, 0,5A, PQ>1W(175MHz)	2a	Tos	BFS22, BFQ42, BFW46, MRF237, 2N3924
2SC549	Si-N	VHF-L, 65V, 1,5A, PQ>5W(175MHz)	49a	Tos	BLY35, 2N3632
2SC55	Si-N	=2SC52: 0,36W	2a		BFX59, (BFW16..17, BFX55)
2SC550	Si-N	VHF-L, 36V, 1,5A, PQ>4W(175MHz)	49a	Tos	BLW35, BLY58, 2N3927
2SC551	Si-N	VHF-L, 65V, 3A, PQ>13,5W(175MHz)	49a	Tos	BLY35, 2N3632
2SC552	Si-N	VHF-L, 36V, 3A, PQ>12W(175MHz)	49a	Tos	BLW36
2SC553	Si-N	UHF-L, 65V, 3A, PQ>10W(175MHz)	49a	Tos	—
2SC554	Si-N	UHF-A/Tr/E, 36V, 0,5A, 400MHz	2a	Tos	BLX65
2SC555	Si-N	UHP-ATr/E, 55V, 0,4A, PQ>1W(400MNz)	2a	Tos	BFR97
2SC556	Si-N	UHF-A/Tr, 40V, 0,4A, 850MHz	2a	Tos	BFR97, 2N3866
2SC557	Si-N	VHF-L, 40V, 2A, 20W, 350MHz	49a	Tos	BLY36, BLY79
2SC556	Si-N	TV-HA, 1500/1500V, 4A, 50W	23a	Tos	BU104, BU606..608, 2SD916, 2SD1154
2SC559	Si-N	Uni, 60V, 0,3A, 0,6W, 230MHz	2a	Tos	BC140..141, BC300..302, 2N3053,++
2SC58	Si-N	Uni, 20V, 25mA, 0,2W	≈2a	Fui	BC168, BC183, BC238, BC548, 2SD767++
2SC560(N)	Si-N	Uni, 60V, 0,8A, 0,8W, 150MHz	2a	Fui, Tos	BC140..141, 2N1990, 2N2102, 2N2405,++
2SC581	Si-N	HF, 20V, 25mA, 0,2W, 200MHz	≈7b	Fui	BF198..199, BF224..225, BF594..595,++
2SC562(Z)	Si-N	HF/ZF, ra, 330MHz	5k	Mat	BF196..199, BF224..225, BF505,++
2SC563(A,AZ)	Si-N	HF/ZF, 40V, 25mA, 550MHz	5k	Mat	BF198..199, BF224..225, BF505,++
2SC564	Si-N	S, 50V, 0,5A, 0,65W, -/65ns	2a	Fui	BSS28..29, BSV77, 2N3724, 2SC1365,++
2SC585	Si-N	S, 50V, 0,2A, 0,35W, -/125ns	2a	Fui	BSV59, BSX48..49, 2N3903..3904,++
2SC566	Si-N	VHF-A/Tr, 50V, 0,3A, 0,8W, 700MHz	5q	Nec	BFX55, 2SC2852
2SC587	Si-N	VHF, ra, 30V, 0,02A, 1300MHz	5q	Nec	BF505, BF689, BF763, 2N2657,++
2SC586	Si-N	VHF, ra, 30V, 0,02A, 900MHz	5q	Nec, Mic	BF505, BF689, BF763, 2N2657,++
2SC569	Si-N	Min, S, 40V, 0,15A, 0,15W, <-/35ns	24b	old	(BSS11, BSX92..93, 2N2368..69(A),++)
2SC57	Si-N	HF-Tr/E, 75V, 0,5A, 110MHz	2a	Nec	(BD139, BD230, 2SD1200, 2SD1376,++)
2SC570	Si-N	=2SC589: 0,2A, 0,3W	6a	old	BSS11, BSX19..20, 2N2368..69(A),++
2SC571	Si-N	VHF-A/Tr/E, 36V, 0,5A, PQ>1W(175MHz)	2a	Mat	BFQ42, BFR96, BFS51, BLW16, BLY61
2SC572	Si-N	VHF-L, 36V, 1A, PQ>4W(175MHz)	49a	Mat	(BLY55, BLY57)
2SC573	Si-N	VHF-L, 36V, 2A, PQ>12W(175MHz)	49a	Mat	(BLY36, BLY79)
2SC574	Si-N	VHF-Tr/E, 60V, 1A, 7,5W, 260MHz	49a	Mat	(BLY60)
2SC575	Si-N	VHF-Tr/E, 60V, 1A, 5W, 210MHz	2a	Mat	(BLY60)
2SC576	Si-N	SS, 40V, 0,5A, 0,36W, <12/15ns	2a	Mat	BSS10, BSX26, BSX39, 2N3261, 2SC4646
2SC577	Si-N	=2SC576: <12/18ns	2a	Mat	BSS10, BSX26, BSX39, 2N3261, 2SC4646
2SC578	Si-N	S, 60V, 0,5A, 0,6W, <65/150ns	2a	Nec	BSS13, BSV77, 2N5169, 2SC1385..1386,++
2SC579	Si-N	S, 30V, 0,2A, 0,36W, <75/50ns	2a	Nec	BSS11..12, BSX19..20, 2N2386..69(A),++
2SC58(A)	Si-N	HF/S, 60..135V, 0,06A, 0,6W, 250MHz	2a	Mat	BF257..259, BF657..659, 2N5058..59
2SC580	Si-N	Uni, 60V, 1A, 0,6W, 250MHz	2a	Nec	BC140..141, 2N1990, 2N2102, 2N2405,++
2SC561	Si-N	HF, 30V, 0,03A, 0,14W, 230MHz	5q	Mat	BF240..241, BF254..255, BF594..595,++
2SC582	Si-N	S/Vid-L, 300V, 0,1A, 6,5W(Tc=70°)	22a	Mat	2SC1505..1507, 2SC1755..1757, 2SC1819,++
2SC583	Si-N	UHF, 30V, 0,02A, 1300MHz	5q	Mat	BF377..378, BF689, BF763, 2N2857,++
2SC584	Si-N	VHF-L, 60V, 2A, 200MHz	49a	Mat	BLY35, 2N3632

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2SC585	Si-N	VHF-L,65V,3A,PQ>13,5W(175MHz)	49a	Mat	2N3632
2SC586	Si-N	S-L,150V,5A,50W,55MHz	23a	Mat	BUW86 67,2SC2837,2SD731 732,++
2SC587(M,N)	Si-N	Uni,45V,0,03A,0,3W,60MHz	2a	Mat,Son,Tos	BC167,BC162,BC237,BC547,2SC1890+
2SC567A(M,N)	Si-N	=2SC587: ra'	2a		BC169,BC164,BC239,BC549,2SC2674+
2SC566	Si-N	Uni,30V,0,1A,0,6W,200MHz	2a	Fui,Son	BC140. 141,BC300. 302,2N2216 19,++
2SC569(N)	Si-N	Vid,165/165V,0,08A,0,75W,200MHz	2a	Mot,Son,Tos	BF257. 259. BF657 659,2N5058. 59,++
2SC59	Si-N	S/VHF/Vid,120V,0,3A,0,8W,150MHz	2a	Nec	BC300,2N1693(A),2N2102,2N2405,++
2SC590(N)	Si-N	Uni,120/70V,0,3A,0,6W,150MHz	2a	Mit,Nec	BC300,2N1693(A),2N2102,2N2405,++
2SC591(N)	Si-N	HF/S-L,100V,1,5A,20W,150MHz	2a	Fui,Nec	(BD139,BD230,BD379,2SD1177 1176)
2SC592	Si-N	VHF-L,75V,2,5A,13W,180MHz	49a	Fui	BLY35,2N3632
2SC593	Si-N	HF,50V,0,03A,0,165W,230MHz	5q	Mat	BF240 241,BF254 255,BF594. 595,++
2SC594(M,N)	Si-N	HF/S,60V,0,2A,0,75W,30/280ns	2a	Fui,Mit,Nec	BSW51 52,BSY58,2N2216..19(A),++
2SC594(M,N)	Si-N			Oki,Tos	—
2SC595(N)	Si-N	S,30V,0,1A,0,3W,450MHz,<100/100ns	2a	Fui,Nec,Oki	BSV90 92,BSX92 93,2N2368. 69(A),++
2SC595(N)	Si-N			Tos	—
2SC596(N)	Si-N	VHF-A/Tr,60V,0,5A,0,6W,400MHz	5q	Fui,Nec	BFX55,BFS23,BLY34
2SC597(N)	Si-N	VHF-A/Tr/E,65V,1A,400MHz	2a	Fui,Mat,Tos	—
2SC598(N)	Si-N	VHF/UHF-L,65V,1,5A,PQ>3,5W(400MHz)	49a	Fui,Mat,Nec	—
2SC598(N)	Si-N			Oki,Tos	—
2SC599(N)	Si-N	VHF-L,60V,1,5A,20W,>300MHz	55r	Mit	BLW23 24,BLY92 93
2SC60	Ge-N	Uni,20V,0,02A,0,1W	2a	Say	AC127,ASY26 28
2SC600(N)	Si-N	VHF-L,65V,3A,PQ=15W(175MHz)	49a	Fui,Mat,Nec	BLY35,2N3632
2SC600(N)	Si-N			Tos	++
2SC601(N)	Si-N	SS,40V,0,1A,0,3W,580MHz,<12/16ns	2a	Fui,Mat	BSV91..92,BSX92 93,2N2368. 69(A),++
2SC602(N)	Si-N	UHF-A/O,30V,0,03A,0,2W,600MHz	5q	Fui,Nec,Tos	BF377. 376,BF669. BF763.2N2857,++
2SC603	Si-N	Dual,Chopper,7V,0,05A,0,2W	≈TO-71	Nec	—
2SC604	Si-N	Min,Uni,45V,0,1A,0,15W	24b	Nec	(BC167,BC162.BC237,BC547.2SD767. +)
2SC605	Si-N	Mn,30V,0,02A,VHF-M.460MHz	24b	Nec	(BF198. 199,BF224. 225,BF505,++)
2SC606	Si-N	Min,VHF-V,530MHz	24b	Nec	(BF225,BF310,BF314,BF505,++)
2SC607	Si-N	HF-Tr/E,75V,0,6A,1W,70MHz	2a	Hit	(BC140 141,BC300. 302,2SC959,++)
2SC606(T)	Si-N	HF-L,75V,1,5A,PQ>1,2W(27MHz)	43m	Hit	(BD139,BD230,BD379,2SD1177 1178)
2SC609(T)	Si-N	=2SC208: PQ>3W(27MHz)	43m	Hit	(BD139,BD230,BD379,2SD1177 1178)
2SC61	Si-N	HF/S,30V,0,3A,1,2W,180MHz	2a	Fui	(BD135,BD226,2SC3419)
2SC610	Si-N	HF/S-L,100V,10A,PQ=32W(40MHz)	38a	Mat	—
2SC611(N)	Si-N	HF,20V,0,02A,1000MHz	5q	Fui,Mat,Nec	BF377 376,BF689,BF763,2N2657,++
2SC611(N)	Si-N			Oki,Tos	—
2SC612(N)	Si-N	HF,35V,0,02A,1300MHz	5q	Mat,Nec,Tos	BF377 376,BF689,BF763,2N2858,++
2SC613	Si-N	S,40V,0,2A,0,36W,<25/25ns	2a	Nec	BSS11,BSX19. 20,2N2366. 69(A),++
2SC614	Si-N	Uni,60V,1,5A,7,5W(Tc=25°),200MHz	2a	Say	BCX40,BSS15 16,BSX45 47,2SD854++
2SC615	Si-N	=2SC614: 30V	2a	Say	BCX40. BSS15 .16,BSX45 47,2SD854++
2SC616	Si-N	=2SC614 13W	2a	Say	(BD139,BD230,BD379,2SD1177 .1176)
2SC617	Si-N	=2SC615: 13W	2a	Say	(BD135,BD226,BD375,2SD1177 .1176)
2SC618(A)	Si-N	VHF,ra,25V,20mA,600MHz	5q	Fui	BF225,BF310,BF314,BF502,BF505++
2SC619	Si-N	Uni,30V,0,2A,0,25W,250MHz	7b	Mit	BC163,BC546,BSV59,2N2221 22(A),++
2SC62	Si-N	S,40V,0,05A,0,36W,<19/75ns	2a	Hrl	BSS11,BSV91. 92,BSX92 93,2N2368++
2SC620(M)	Si-N	=2SC619: 50V	7b	Mit	BC182,BC547,BSV59,2N2221 22(A),++
2SC621(AM)	Si-N	HF/S,70/70V,0,4A,0,15W,150MHz	5c	Mit	BC168,BC183,BC236,BC546,2SD767++
2SC622	Si-N	40V,0,8A,300MHz	2a	Mit	BC166,BC183,BC236,BC548,2SD767++
2SC623	Si-N	Min,S,40V,0,15A,0,15W,<-/90ns	24b	old	(BSS11,BSX92 93,2N2368 69(A),++)
2SC624	Si-N	=2SC623. 0,2A,0,3W	6a	old	BSS11,BSX92. 93,2N2368 69(A),++
2SC625	Si-N			old	—
2SC628	Si-N	HF-ATr/E,50V,0,2A,0,75W,350MHz	2a	Nec	BFW16 .17,BFX55
2SC627(F)	Si-N	Vid,200V,0,1A,0,7W,20MHz	2a	Fui	BF258. 259,BF656 659,2N5058..59
2SC626	Si-N	VHF-Tr/E,40V,0,5A,PQ=2W(200MHz)	2a	Nec	BFW46,BLY33,BLX65,2N3924
2SC629	Si-N	UHF,18V,0,03A,800MHz	Son	Son	BF377 378,BF689K,BF763,2N2657,++
2SC63	Si-N	S,25V,0,05A,0,3W,400MHz	2a	Nec	BSY62 63,BSW41,2N706A 2N708,++
2SC630	Si-N			Son	—
2SC631(A,S)	Si-N	=2SC632(A): ra,25V	10b	Son	BC169,BC184,BC239,BC549,2SC2675+
2SC632(A)	Si-N	Uni,50V,0,1..0,2A,140MHz	10b	Son	BC167,BC162,BC237,BC547,2SD767++
2SC633(A)	Si-N	Uni,25V,0,1..0,2A,140MHz	10b	Son	BC166,BC163,BC236,BC548,2SD767++
2SC634(A)	Si-N	=2SC633(A): 50V	10b	Son	BC167,BC162,BC237,BC547,2SD767++
2SC635	Si-N	VHF-L,65V,1,5A,PQ>4W(175MHz)	49a	Nec	BLY60
2SC636	Si-N	VHF-L,65V,3A,PQ>7,5W(260MHz)	49a	Nec	BLY35,2N3632
2SC637	Si-N	VHF-L,40V,1A,PQ=6W(175MHz)	49a	Nec	BLY57,2N3926
2SC636	Si-N	VHF-L,40V,2A,PQ=13,2W(175MHz)	49a	Nec	BLY56,2N3927
2SC639	Si-N	SS,40V,0.2A,0.36W,<12/18ns	2a	Nec	BSS11,BSX19. 20,2N2368. 69(A),++

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2SC64	Si-N	HF/Vid, 80V, 0,05A, 0,6W, 100MHz	2a	Say	BF257..259, BF657..659, 2N5058..59
2SC640	Si-N	Min, Uni, 30V, 0,1A, 0,15W, 100MHz	24b	Nec	(BC168, BC183, BC238, BC548, 2SD767,++)
2SC641(H,K)	Si-N	HF/NF/S, 40V, 0,1A, 400MHz, 20/35ns	9b,7c	Hit	BFX59, BSV91..92, BSX92..93, 2SC2851
2SC642	Si-N	TV-VA, 1100/700V, 1A, 50W	23a	Tos	BU204..206, 2SC1922, 2SD575, 2SD818,++
2SC642A	Si-N	=2SC642: 1500/800V	23a		BU204..206, 2SC1922, 2SD575, 2SD818,++
2SC643	Si-N	TV-HA, 1100V, 2,5A, 50W	23a	Tos	BU204..206, 2SC1922, 2SD575, 2SD818,++
2SC643A	Si-N	=2SC642 1500V	23a		BU204..206, 2SC1922, 2SD575, 2SD818,++
2SC644	Si-N	Uni, ra, 30V, 0,05A, 0,25W, 160MHz	7c	Mat, Mic	BC169, BC184, BC239, BC549, 2SC2675+
2SC645(Z)	Si-N	HF, 30V, 0,03A, 0,14W, 200MHz	≈2b	Mat	BF240..241, BF254..255, BF594..595,++
2SC646	Si-N	NF/S-L, 60V, 4A, 25W, 50MHz	23a	Mat	2SC2681, 2SC2706, 2SC2837, 2SC3258
2SC647	Si-N	NF/S-L, 80V, 5A, 50W(Tc=70°), 43MHz	23a	Mat	2SC2681, 2SC2706, 2SC2837, 2SC3256
2SC648(H)	Si-N	NF/HF, ra, 30V, 0,03A, 0,1W, 350MHz	2a	Hit	BF198..199, BF224..225, BF505,++
2SC649	Si-N	Uni, ra, 30V, 0,03A, 0,2W, 220MHz	2a	Hit	BC169, BC184, BC239, BC549, 2SC2675+
2SC65(Y)	Si-N	=2SC64: 150V, 200MHz	2a	Say	BF257..259, BF657..659, 2N5058..59
2SC650	Si-N	Uni, ra, 30V, 0,03A, 0,2W, 220MHz	2a	Hit	BC169, BC184, BC239, BC549, 2SC2675+
2SC651	Si-N	VHF/UHF-A/Tr, 45V, 0,3A, PQ>0,75W(500MHz)	2a	Nec	BFS50, MRF515, 2N3948, 2SC2852,++
2SC652(M)	Si-N	VHF/UHF-A/Tr, 40V, 0,3A, PQ>1W(500MHz)	2a	Nec	BFS50, MRF515, 2N3948, 2SC2852,++
2SC653	Si-N	UHF, 25V, 0,02A, 1400MHz	5q	Nec	BF377..378, BF689, BF763, 2N2857,++
2SC654	Si-N	VHF-A/Tr/E, 40V, 0,3A, 0,8W, 650MHz	5q	Nec	BFR98, BFX55, MRF207, MRF225,++
2SC655	Si-N	Min, NF/HF, 10V, 10mA, 80MHz	4-SIP	Mat	—
2SC656	Si-N	Min, HF, 10V, 5mA, 550MHz	4-SIP	Mat	—
2SC657	Si-N	VHF-VM/O, 18V, 0,03A, 500MHz	10b	Son	BF198..199, BF224..225, BF505,++
2SC658(M)	Si-N	VHF-VM/O, 25V, 0,5A, 550MHz	5c	Mit	BF198..199, BF224..225, BF505,++
2SC659	Si-N	=2SC658: 400MHz	5c	Mit	BF198..199, BF224..225, BF505,++
2SC66	Si-N	=2SC64 150V, 130MHz	2a	Say	BF F8870257..259, BF657..659, 2N5058..59
2SC660	Si-N	VHF, re, 25V, 0,02A, 600MHz	4q	Mit	BF225, BF310, BF314, BF502, BF505++
2SC661	Si-N	VHF, re, 25V, 0,02A, 600MHz	4q	Mit	BF225, BF310, BF314, BF502, BF505++
2SC662	Si-N	UHF-VM/O, 25V, 0,02A, 800MHz	5q	Mit	BF377..378, BF669, BF763, 2N2857,++
2SC663	Si-N	UHF-VM/O, 25V, 0,02A, 900MHz	5q	Mit	BF377..378, BF689, BF763, 2N2857,++
2SC664	Si-N	NF/S-L, 100V, 5A, 50W, 15MHz	23a	Hit	BD245C, BDV95, BDX95, 2SC2681,++
2SC665(H)	Si-N	=2SC664: 125V	23a	Hit	BD245D, 2SC2706, 2SC2837, 2SD551,++
2SC666	Si-N	=2SC664: 150V	23a	Hit	BD245D, 2SC2837, 2SD551, 2SD1046,++
2SC667	Si-N	HF, 15V, 0,03A, 0,12W, 600MHz	≈7c	Say	BF198..199, BF224..225, BF505,++
2SC668	Si-N	=2SC667, ra	≈7c	Say	BF314, BF502, BF505, BF507,++
2SC668SP	Si-N	=2SC866: 0,15W	41c		→2SC668
2SC669(A)	Si-N	NF/S, 100V, 3A, 10W(Tc=25°), 85MHz	2a	Son	BSX84, 2N4239, 2SC2214
2SC67	Si-N	S, 40V, 0,2A, 0,36W, 400MHz, <20/40ns	2a	Nec	BSS11, BSX19..20, 2N2368..69(A),++
2SC670..873	Si-N			Son	—
2SC674	Si-N	VHF-VM/O, 600MHz	≈7c	Say	BF198, BF225, BF314, BF502, BF505++
2SC674SP	Si-N	=2SC674: 0,15W	41c		→2SC674
2SC675	Si-N	S-L, 250/120V, 7A, 50W, -/<3µs	23a	Nec	BD550B, BU606..608, BUX18A..C,++
2SC876	Si-N	=2SC675: 200/100V	23a	Nec	BD245F, BU606..608, BUX18A..C,++
2SC677	Si-N	=2SC675: 150/60V, -/<4,5µs	23a	Nec	BD245D, BU606..606, BUX18A..C,++
2SC678	Si-N	=2SC675: 100/60V, -/<4,5µs	23a	Nec	BD245C, BU606..608, BUX18A..C,++
2SC679	Si-N	TV-VA, 300V, 2A, 30W, 20MHz	22a	Hit	BU406..408, 2SC779, 2SC825, 2SD1150,++
2SC68(M)	Si-N	S, 40V, 0,2A, 0,36W, 400MHz, <20/40ns	2a	Nec	BSS11, BSX19..20, 2N2368..69(A),++
2SC680(A)	Si-N	TV-VA, 200/120(A=140)V, 2A, 30W, 20MHz	22a	Hit	BU406..408, 2SC779, 2SC825, 2SC1025,++
2SC681	Si-N	HV, TV-HA, 800/325V, 10A, 50W	23a	Hit	BU104, BU606..606, 2SD916
2SC681A,ARD	Si-N	=2SC661: 250/80V	23a		BU104, BU606..606, 2SD916
2SC661AYL	Si-N	=2SC681: 300/80V	23a		BU104, BU606..606, 2SD916
2SC662	Si-N	TV-ZF, re, 20V, 0,02A, 550MHz	5q	Hit	BF198, BF225, BF310, BF367, BF596++
2SC683	Si-N	VHF, re, 20V, 0,02A, 550MHz	5q	Hit	BF198, BF225, BF310, BF367, BF596++
2SC664	Si-N	UHF-O, 30V, 0,05A, 1100MHz	9b	Hit	BF377..378, BF689K, BF783, 2N2857,++
2SC685(A,H)	Si-N	NF/Vid-E-L, 300/300V, 0,1A, 4W, 25MHz	22a	Hit	2SC1505..1507, 2SC1755..1757, 2SC1905,++
2SC666	Si-N	Vid, 150/150V, 0,05A, 0,8W, 180MHz	2a	Nec	BF257..259, BF657..659, 2N5058..59
2SC667	Si-N	S-L, 150V, 5A, 50W, -/<3µs	23a	Mat	BD245D, BU606..608, 2SD731..732,++
2SC666	Si-N	VHF-L, 60V, 1,5A, 20W, 300MHz	55r	Mit	BLY97..98, 2N5641
2SC689(H)	Si-N	SS, 40V, 0,1A, 0,3W, >600MHz, 6.5/8ns	2a	Hit	BSV91..92, BSX92..93, 2N2368..69(A),++
2SC69	Si-N	HF/S, 120V, 0,3A, 0,8W, 160MHz	2a	Nec	BC300, BSY55..56, 2N1893(A),++
2SC690(A,M)	Si-N	VHF-L, 60V, 3(A=4)A, PQ=25W(150MHz)	55r	Mit	BLX39, MRF314A, MRF315A
2SC691(M)	Si-N	VHF-Tr/E, 60V, 0,5A, PQ=3,5W(150MHz)	55r	Mit	BLY91
2SC692	Si-N	VHF-L, 60V, 1A, PQ=9W(150MHz)	55r	Mit	BLY92
2SC693(FP,NP)	Si-N	Uni, ra, 40V, 0,05A, 0,1W, 150MHz	≈7c,7c	Say, Mic	BC184, BC413..414, BC550, 2SC2390,++
2SC694(FP)	Si-N	Uni, ra, 40V, 0,05A, 0,1W, 100MHz	≈7c,7c	Say	BC184, BC413..414, BC550, 2SC2390,++
2SC695	Si-N	NF, ra, 20V, 0,03A, 0,1W, 150MHz	24b	Nec	(BC169, BC184, BC239, BC549, 2SC2390,++)
2SC696(Z)	Si-N	Uni, 100V, 3A, 0,75W, 100MHz	2a	Mat	BSX84, 2N4239, 2SC2214

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2SC696A	Si-N	=2SC696: 130V	2a		BU125S, BUX49..50, BUY41, 2SD625
2SC697	Si-N	=2SC696: 10W	43m	Mat	(BD791, BDX35..37, MJE243..244)
2SC697A	Si-N	=2SC696: 130V, 10W	43m		(BDV11, BDX36..37, 2SD772)
2SC698	Si-N	NF/HF/S-L, 100V, 3A, 10W, 90MHz	43m	Nec	(BD791, BDX35..37, MJE243..244)
2SC699	Si-N	HF-E, 50V, 1A, 10W, 100MHz	43m	Mit	(BD137, BD228, BD377, 2SD1177..78++)
2SC70	Si-N	Vid, 180V, 0,02A, 0,8W, 130MHz	2a	Tos	BF258..259, BF658..659, 2N5058..59
2SC700	Si-N	VHF-A/Tr, 80V, 0,75A, 300MHz	2a	Mit	BFS23, BLY34
2SC701	Si-N	VHF-A/Tr, 40V, 0,75A, 500MHz	2a	Mit	BFS22, BFW46, BLY33, MRF237, 2N3924
2SC702	Si-N	VHF-L, 40V, 0,75A, PQ=3W(175MHz)	55r	Mit	BLY85, 2N5589
2SC703	Si-N	VHF-L, 40V, 2A, PQ=12W(175MHz)	55r	Mit	BLW19, MRF208, MRF212, 2N5590
2SC704	Si-N	VHF-L, 40V, 4A, PQ=17W(175MHz)	55r	Mit	BLY89, MRF209, 2N5591, 2N6082
2SC705	Si-N	VHF, 15V, 0,03A, 700MHz	≈7c	Say	BF225, BF314, BF502, BF505, BF507++
2SC706	Si-N	=2SC705: 800MHz	≈7c	Say	BF225, BF314, BF502, BF505, BF507++
2SC707(H)	Si-N	UHF, 650MHz	5q	Hit	BF377..378, BF689, BF763, 2N2857, ++
2SC708(H)	Si-N	Uni, 80V, 1A, 0,75W, 15MHz	2a	Hit	BC140..141, 2N1990, 2N2102, 2N2405, ++
2SC708A	Si-N	=2SC708: 100V	2a		BC141, 2N1990, 2N2102, 2N2405, ++
2SC709	Si-N	Uni, 25V, 0,1A, 0,2W, 180MHz	7b	Mit	BC168, BC183, BC238, BC548, 2SD767++
2SC71	Ge-N	S, 18V, 0,2A, 0,15W	2a	Tos	AC127, ASY28..29, ASY73..75
2SC710	Si-N	Uni, AM/FM, 30V, 0,03A, 0,2W, 200MHz	7b	Mit	BC548, BF240..241, BF254..255, ++
2SC711	Si-N	Uni, 30V, 0,05A, 0,2W, 150MHz	7b	Mit	BC168, BC183, BC238, BC548, 2SC1890+
2SC711A	Si-N	=2SC711: 50V	7b		BC187, BC182, BC237, BC547, 2SC1890+
2SC712(A)	Si-N	Uni, 30V, 0,1A, 0,2W, 150MHz	7b	Mit	BC188, BC183, BC238, BC548, 2SC1890+
2SC713(M)	Si-N	S, 30V, 0,1A, 0,2W, <60/150ns	7b	Mit	BSW41, BSY83, 2N708, 2N4123..24, ++
2SC714	Si-N	S, 70V, 0,2A, 0,25W, <40/250ns	7b	Mit	BSW83..64, 2N2221..22(A)
2SC715	Si-N	Uni, 40V, 0,1A, 0,125W, 140MHz	≈7c	Mit, Say	BC187, BC183, BC237, BC547, 2SC1815+
2SC716	Si-N	=2SC715: 20V	≈7c	Mit, Say	BC168, BC183, BC238, BC548, 2SC1740+
2SC717	Si-N	VHF-VM/O, >600MHz	9b	Hit	BF225, BF314, BF502, BF505, BF507++
2SC718	Si-N	SS, 20V, 0,2A, 0,3W, 800MHz, -/15ns	2a	Fui	BSS10..12, BSY17..18, 2N2368..69(A), ++
2SC719	Si-N	=2SC718: 0,2W	2a	Fui	BSS10..12, BSY17..18, 2N2368..69(A), ++
2SC72	Ge-N	S, 18V, 0,2A, 0,15W	2a	Tos	AC127, ASY28..29, ASY73..75
2SC720	Si-N	TV-ZF, re, 25V, 0,02A, 500MHz	5q	Fui, Say	BF196, BF225, BF310, BF367, BF596++
2SC721	Si-N	=2SC720:	≈2b	Fui, Say	BF198, BF225, BF310, BF367, BF596++
2SC722	Si-N	VHF/UHF, 25V, 25mA, 700MHz	≈2b	Fui, Say	BF377..378, BF689K, BF783, 2N2857, ++
2SC723	Si-N	VHF/UHF, 25V, 25mA, 500MHz	≈2b	Fui, Say	BF377..378, BF689K, BF783, 2N2857, ++
2SC724	Si-N	HF/S, 30V, 0,2A, 0,2W, 250MHz, -/<300ns	7c	Fui	BC168, BC183, BC238, BC548, 2SC1815+
2SC725	Si-N	=2SC724: 60V	7c	Fui	BC174, BC182, BC190, BC548, 2SD787++
2SC726	Si-N	SS, 20V, 0,2A, 0,2W, 800MHz, -/15ns	≈2b	Fui, Say	BSS10..12, BSY17..18, 2N2368..69(A), ++
2SC727	Si-N	Nix, Vid, 100/100V, 0,1A, 0,35W, 20MHz	2a	Fui	BF297..299, BSS38, BSX21, 2SC3467, ++
2SC728	Si-N	=2SC727: 200/200V	2a	Fui	BF297..299, BF391..393, 2SC3467, ++
2SC729	Si-N	Uni, 50V, 0,2A, 0,6W, 250MHz	2a	Nec	BC140..141, BC300..302, 2N3053, ++
2SC73	Ge-N	HF, 15V, 5mA, 0,03W, 20MHz	≈2e	Son	—
2SC730	Si-N	VHF-A/Tr/E, 40V, 0,4A, PQ=1,5W(150MHz)	2a	Mit	BFR98, BLW18, MRF225, MFR807, ++
2SC731(Z)	Si-N	UHF-/VTr/E, 40V, 0,5A, PQ=1,2W(500MHz)	2a	Mat	BFS50, MRF629, 2N3948
2SC732(TM)	Si-N	Uni, ra, 3580V, 0,1A, 0,3W, 80MHz	7c	Tos	BC550, 2SC2240, 2SC2459, 2SC2674..75, ++
2SC733	Si-N	Uni, 35V, 0,1A, 0,3W, >60MHz	7c	Tos	BC168, BC183, BC238, BC548, 2SD767++
2SC734	Si-N	Uni, 70V, 0,15A, 0,3W, 150MHz	7c	Tos	BC546, 2SC1627, 2SC2003
2SC735	Si-N	Uni, 35V, 0,4A, 0,3W, 300MHz	7c	Tos	BC337..338, BC635, BC637, 2SC3377, ++
2SC736	Si-N	S-L, 135V, 5A, 50W, <2/4µs	23a	Nec	BD550, BU606..606, 2SC2706, 2SD1046, ++
2SC737(M)	Si-N	VHF-L, 80V, 1,5A, PQ=14W(150MHz)	55r	Mit	BLW24, BLY92
2SC738	Si-N	VHF, 25V, 20mA, 440MHz	7b	Mit	BF198..199, BF224..225, BF505, ++
2SC739	Si-N	=2SC738: 350MHz	7b	Mit	BF196..199, BF224..225, BF505, ++
2SC74	Si-N	Uni, 50V, 0,1A, 0,8W, 300MHz	2a	Tos	BC300..302, BSY58, 2N3299..3300, ++
2SC740	Si-N	=2SC738: UHF, 900MHz	5c	Mit	BF377..378, BF689, BF763, 2N2857, ++
2SC741	Si-N	VHF-A/Tr/E, 40V, 0,3A, PQ=0,3W(150MHz)	2a	Mit	BFX55, 2SC2852
2SC742	Si-N	VHF-L, 65V, 1,5A, 12,5W, 400MHz	49a	Fui	BLY35, BLY60, 2N3632
2SC743	Si-N	VHF-L, 65V, 3A, 25W, 350MHz	49a	Fui	BLY35, 2N3632
2SC744	Si-N			Fui	—
2SC745	Si-N	VHF-L, 50V, 1,5A, 12,5W, 450MHz	49a	Fui	BLY35, BLY80, 2N3632
2SC746	Si-N	VHF-L, 45V, 3A, 25W, 350MHz	49a	Fui	BLY35, 2N3632
2SC748	Si-N	VHF-L, 36V, 1A, 12,5W, 400MHz	49a	Fui	BLY35, BLY80, 2N3632
2SC749	Si-N	VHF-L, 36V, 2A, 25W, 350MHz	49a	Fui	BLY35, 2N3632
2SC75	Ge-N	AM-ZF, 15V, 5mA, 10MHz	≈2e	Son	—
2SC750	Si-N			Fui	—
2SC751	Si-N	VHF, 20V, 0,02A, 650MHz	2a	Tos	BF196..199, BF224..225, BF505, ++
2SC752(G,GTM)	Si-N	Uni, S, 30V, 0,1A, 0,1W, 300MHz	7c	Tos	BC168, BC183, BC238, BC548, 2SD767++
2SC753	Si-N	UHF, 1100MHz	24b	Nec	BF382..383

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2SC754	Si-N	Uni, 20V, 0,15A, 0,15W, 90MHz	94h	Nec	(BC168, BC183, BC238, BC548, 2SD767, ++)
2SC755	Si-N	Uni, 15V, 0,1A, 0,15W, 100MHz	24b	Nec	(BC168, BC183, BC238, BC548, 2SD767, ++)
2SC756(A-...)	Si-N	NF/S, 80 150V, 4A, 10W(Tc=25°), 65MHz	2a	Son	BUX34, BUY80, 2SD625
2SC757	Si-N	UHF, 1100MHz	24b	Nec	BF362 363
2SC758	Si-N	S-L, 280/120V, 8A, 80W, 18MHz	23a	old	BD550B, BU606 606, BUX18A C, ++
2SC759	Si-N	=2SC758: 180/100V	23a	old	BD245E, BU606..608, BUX18A. C, ++
2SC76	Ge-N	AM-ZF, 15V, 5mA, 10MHz	≈2e	Son	—
2SC760	Si-N	=2SC758: 100/60V	23a	old	BD245C, BU606 .606, BUX18AC, ++
2SC761(Z)	Si-N	UHF, re, 30V, 0,02A, 675MHz	5q	Mat	BF377 .376, BF689, BF763, 2N2857, ++
2SC762(Z)	Si-N	UHF, re, 30V, 0,02A, 800MHz	5q	Mat	BF377 .378, BF669, BF783, 2N2857, ++
2SC763	Si-N	VHF, 25V, 20mA, >400MHz	7b	Mit	BF225, BF310, BF314, BF502, BF505++
2SC764	Si-N	SS, 40V, 0,2A, 0,36W, <12/18ns	2a	Nec	BSS11, BSX19..20, 2N2368 .89(A), ++
2SC765	Si-N	AM-L, 80V, 2A, PQ=20W(27MHz)	23a	Mit	—
2SC766	Si-N	AM-L, 120V, 2A, PQ=19W(27MHz)	23a	Mit	—
2SC767	Si-N	AM-L, 160V, 2A, PQ=19W(27MHz)	23a	Mit	—
2SC768	Si-N	S-L, 80/40V, 10A, 50W, -/<3µs	23a	Mit	BD245A, BD311, BDV91, 2N3055, ++
2SC769	Si-N	=2SC768: 120/80V	23a	Mit	BD245D, BDX51, 2N5633..34, 2SD551, ++
2SC77	Ge-N	AM-ZF, 15V, 5mA, 10MHz	≈2e	Son	—
2SC770	Si-N	=2SC768: 200/100V	23a	Mit	BD245F, BUX17A..C, 2SC3263, 2SD555, ++
2SC771	Si-N	=2SC768: 250/120V	23a	Mit	BUX17AC, BUY18, 2SC3263, 2SD555, ++
2SC772	Si-N	NF/S, 15V, 0,03A, 0,12W, 300MHz	≈7c	Say	BF198..199, BF224..225, BF254..255, ++
2SC773	Si-N	AM-O, 50V, 0,2A, PQ=40mW(27MHz)	7b	Mit	2SC2086, 2SC2851, (BC237, BC546, ++)
2SC774	Si-N	AM-CVTr, 50V, 0,5A, PQ=0,07W(27MHz)	2a	Mit	MRF402, MRF8003, 2SC761
2SC775	Si-N	AM-Tr/E, 75V, 1A, PQ=0,7W(27MHz)	2a	Mit	2SC781
2SC776	Si-N	AM-Tr/E, 75V, 1A, PQ=1,5W(27MHz)	2a	Mit	—
2SC777	Si-N	AM-E, 75V, 1A, PQ=3,5W(27MHz)	43m	Mit	(2SC1306, 2SC1909, 2SC2020, 2SC2029, ++)
2SC776	Si-N	AM-E, 80V, 2A, PQ=4W(27MHz)	43m	Mit	(2SC1306, 2SC1909, 2SC2020, 2SC2029, ++)
2SC779	Si-N	S-L, TV-HA, 300/250V, 2A, 25W, 6MHz	22a	Tos	2SC825, (BU406..408, 2SD1150, 2SD1183, ++)
2SC76	Si-N	AM-V/M/O, 15V, 5mA, 20MHz	≈2e	Son	—
2SC780(G,GTM)	Si-N	Nix, Vid, 70/70V, 0,02A, 100MHz	7c	Tos	BF297 .299, BF422, BSW32, BSS36, ++
2SC780A(G,GTM)	Si-N	=2SC760: 150/150V	7c		BF297 .299, BF422, 2SC2375, 2SD2030, ++
2SC781	Si-N	AM-Tr/E, 75V, 1A, PQ=0,6W(27MHz)	2a	Nec	BFS23, BLY34
2SC782(A)	Si-N	S-L, 300/300V, 1,5A, 20(A=25)W, 10MHz	22a	Tos	2SC779, 2SC825, (BUX64..65, 2SD1150, ++)
2SC783	Si-N	=2SC762: 200/200V	22a	Tos	2SC779, 2SC825, (BU408. 406, 2SD1136, ++)
2SC784	Si-N	FM-V, 40V, 0,02A, 500MHz	7c	Tos	BF241, BF255, BF314, BF495, BF595++
2SC785	Si-N	FM-M/O, 40V, 0,02A, 500MHz	7c	Tos	BF240, BF254, BF310, BF494, BF595++
2SC786	Si-N	FM/VHF, 20V, 0,02A, >250MHz	5q	Tos	BF225, BF310, BF314, 2SC1393..91, ++
2SC767	Si-N	UHF, 25V, 0,02A, 1000MHz	5q	Tos	BF377 .378, BF669K, BF763, 2N2857, ++
2SC768	Si-N	Vid, 250/150V, 0,05A, 0,8W, 120MHz	2a	Tos	BF258..259, BF858 .659, 2N5056 59
2SC789	Si-N	NF/S-L, 70V, 4A, 30W, >3MHz	17j	Tos, Mic	BD243A, BD537, BD539B, BD951, ++
2SC79	Si-N	VHF, 15V, 50mA, 500MHz	2a	Fui	BF198..199, BF224..225, BF505, ++
2SC790	Si-N	NF/S-L, 50V, 3A, 25W, >3MHz	17j	Tos, Mic	BD241, BD243, BD535, BD935, ++
2SC791	Si-N	S-L, TV-VA, 90/60V, 1,5A, 15W	22a	Tos	BD239B, 2SC779, 2SC782 .783, 2SC825, ++
2SC792	Si-N	S-L, TV-SN, 400/300V, 1,5A, 50W, 10MHz	23a	Tos	BU126, 2SC1295, 2SD1503
2SC793	Si-N	NF/S-L, 100V, 7A, 60W, 9MHz	23a	Tos	BD245C, BDV95, BDX95, 2N5632. 33, ++
2SC794	Si-N	=2SC793: 70V	23a	Tos	BD245A, BDV93, BDX93, 2N5874, ++
2SC795	Si-N	Vid-L, 250/200V, 0,1A, 9W, 160MHz	22a	Son	2SC1505..1507, 2SC1755..1757, 2SC1905
2SC796	Si-N	AM/FM-Tr/E, 40V, 0,5A, 0,5W, 230MHz	2a	Fui	BFQ42, BFR96, BFS51, BLW16, ++
2SC797	Si-N	AM-Tr/E, 80V, 0,5A, PQ=1,3W(27MHz)	2a	Fui	—
2SC798	Si-N	AM-/E, 60V, 1,5A, PQ=3,5W(27MHz)	2a	Fui	—
2SC799	Si-N	AM-/L, 60V, 1,5A, PQ=3,5W(27MHz)	43m	Nac	(2SC1306, 2SC1909, 2SC2020, 2SC2029, ++)
2SC80	Si-N	VHF-V/M/O, 30V, 60mA, 200MHz	5q	Nec	BF198..199, BF224. 225, BF505, ++
2SC800	Si-N	VHF/UHF, 30V, 0,01A, 600MHz	24b	Nec	BF362. 363
2SC801	Si-N	NF/HF/S-L, 75V, 0,5A, 13W, 100MHz	2a	Nec	(BD189, BD230, BD377, 2SD1200, ++)
2SC602	Si-N	AM-Tr/E, S, 80V, 0,5A, PQ=1,3W(27MHz)	2a	Fui	MRF229. 230, MRF402
2SC603	Si-N	AM-Tr/E, S, 80V, 1,5A, PQ=3,5W(27MHz)	2a	Fui	—
2SC804	Si-N	VHF/UHF, 15V, 0,02A, 1200MHz	24f	Son	BF362 363
2SC805	Si-N	Uni, Vid, 100/100V, 0,2A, 0,75W, 180MHz	2a	Son	BF257 .259, 2SC3245(A), 2SC3248, ++
2SC805A	Si-N	=2SC805: 240/150V	2a		BF258..259, BFR58..59, 2SC3468
2SC606	Si-N	S-L, 650V, 10A, 125W, 5,5MHz	23a	Son	BUS12(A), BUW26, BUW35 36, BUX60, ++
2SC806A	Si-N	=2SC806: 700/200V	23a		BUS12(A), BUW26, BUW35..36, BUX80, ++
2SC807	Si-N	S-L, 500/220V, 10A, 125W, 5,5MHz	23a	Son	BUW25, BUW34, BUW75, 2SC3046, ++
2SC807A	Si-N	=2SC807: 580/200V	23a		BUW25, BUW34, BUW75, 2SC3046, ++
2SC606	Si-N	S-L, 300/100V, 5A, 80W, 12MHz	23a	Son	BU606..608, BUW71, BUX18A..C, ++
2SC809	Si-N	UHF, 25V, 20mA, 1200MHz	5q	Fui	BF377..378, BF689, BF763, 2N2857, ++
2SC81	Si-N	NF/S-L, 50V, 5A, 125W		Mit	(BD245, BDV91, 2SD895..696, 2SD718, ++)

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2SC810	Si-N	VHF-A/Tr, 40V, 0,3A, 0,5W, 750MHz	5q	Fui	BFX55, 2SC2852
2SC811	Si-N	VHF/UHF, 35V, 0,03A, 800MHz	5q	Fui	BF377..378, BF689, BF763, 2N2857, ++
2SC812(F)	Si-N	SS, 20V, 0,1A, 0,25W, <-/27ns	2a	Fui	BSS11..12, BSX27, BSY17..18, 2N2475++
2SC813	Si-N			Fui	—
2SC814	Si-N	NF-E, 30V, 0,5A, 0,4W, 180MHz	7c"	Nec	BC337..337, BC635, BC637, 2SC3377, ++
2SC815(S)	Si-N	Uni, 80V, 0,2A, 0,25W, 200MHz	7c	Nec, Mic	BC174, BC182, BC190, BC546, 2SC2675+
2SC816	Si-N	Uni, 80V, 1A, 1W, 140MHz	2a	Mit	BC140..141, 2N1990, 2N2102, 2N2405, ++
2SC817	Si-N	UHF, 30V, 0,02A, >550MHz	5q	Mit, Mic	BF377..378, BF889, BF763, 2N2857, ++
2SC818	Si-N	Vid, 160/120V, 0,1A, 0,8W, 100MHz	2a	Mit	BF257..259, 2N5058..59, 2SC3248, ++
2SC819	Si-N	VHF-Tr/E, 65V, 1A, 6W, 500MHz	2a	Hit	BFS23, BLY34
2SC82	Si-N	=2SC81: 100V		Mit	(BD245C, BDV93, 2SD718, 2SD896, ++)
2SC820	Si-N	VHF-L, 65V, 1,5A, 10W, 500MHz	49a	Hit	BLY35, BLY80, 2N3632
2SC821(Z)	Si-N	VHF-A/Tr, 40V, 0,3A, PQ>1W(175MHz)	2a	Mat	BFX55, MRF225, MRF607, 2SC2852
2SC822(Z)	Si-N	VHF-A/Tr, 40V, 0,5A, PQ>1,7W(175MHz)	2a	Mat	BFS22, BFW46, BLY33, 2N3924
2SC823	Si-N	VHF/UHF, ra, 30V, 0,06A, 1500MHz	5q	Nec	BFR95, BFS50, MRF515
2SC824	Si-N	VHF/UHF, ra, 50V, 0,12A, 1300MHz	5q	Nec	BFR95, 2N3866, 2N4428
2SC825	Si-N	S-L, TV-HA, 300/300V, 2A, 30W, 15MHz	22a	Fui	2SC779, (BU408..408, 2SD1150, 2SD1163, ++)
2SC826	Si-N	Uni, 100V, 0,3A, 0,7W, 20MHz	2a	Fui	BC141, BC300, 2N1889..90, 2N1893(A), ++
2SC827	Si-N	Uni, 100V, 0,5A, 0,7W, 20MHz	2a	Fui	BC141, BC300, 2N1889..90, 2N1893(A), ++
2SC828(Z)	Si-N	Uni, 30V, 0,05A, 0,25W, 220MHz	7c	Mat, Mic	BC188, BC163, BC238, BC548, 2SC1890+
2SC828A(Z)	Si-N	=2SC828: 45V	7c		BC187, BC182, BC237, BC547, 2SC1890+
2SC829(Z)	Si-N	AM/FM-VM/O, 30V, 30mA, 230MHz	7c	Mat, Mic	BF240..241, BF254..255, BF594..595, ++
2SC83	Si-N	=2SC81: 150V		Mit	(2SC2837, 2SD731, 2SD1046..1047, ++)
2SC830	Si-N	NF/S-L, 50V, 3A, 25W, 20MHz	22a	Hit	BD241, BD535, BD935, 2N4231..33, ++
2SC830H	Si-N	=2SC830: 100V, 8MHz	22a		BD241C, BD937, 2N4233, 2SD712, ++
2SC831	Si-N	VHF-L, 50V, 2A, PQ=12W(260MHz)	49a	Nec	BLY35, 2N3632
2SC833(N)	Si-N	S-L, 450/300V, 2A, 25W, >10MHz, <2/3µs	22a	Fui, Hit, Say	BUW40, BUY63..64, 2N4240, 2N3585, ++
2SC833(N)	Si-N			Tos	—
2SC636	Si-N	VHF, ra, 30V, 0,02A, 600MHz	7c	Nec	BF225, BF310, BF314, BF502, BF505++
2SC837	Si-N	TV-ZF, 30V, 0,02A, 550MHz	7c	Nec	BF198..199, BF224..225, 2SC2215..16, ++
2SC838	Si-N	AM/FM-VM/O, 50V, 0,05A, 250MHz	7c	Nec, Mic	BF240..241, BF254..255, 2SC2210, ++
2SC839	Si-N	=2SC838: ra	7c	Nec	BF241, BF255, BF495, BF595, 2SC2210+
2SC64	Ge-N	S, 25V, 0,2A, 0,12W, -/700ns	2a	Mit	ASY28..29, ASY73..75
2SC840	Si-N	NF/S-L, 100/60V, 2A, 20W, 50MHz	22a	Mat	BD239C, BDY72, 2N3441, 2SC2528..2529++
2SC640A	Si-N	=2SC840: 150/100V	22a		BDY72, 2N3441, 2SC2529, 2SD759..780, ++
2SC641(H)	Si-N	VHF-Tr/E, 36V, 0,5A, 450MHz	2a	Fui, Hit	BFQ42, BFR98, BFS51, BLW16, BLY61
2SC642	Si-N	VHF-L, 38V, 1A, 10W, 450MHz	49a	Fui, Hit	BLY55, BLY57, BLY78, 2N3926
2SC843	tsi-N	VHF-L, 36V, 2A, 20W, 350MHz	49a	Fui, Hit	BLY38, BLY79
2SC644	Si-N	VHF-Tr/E, 40V, 0,4A, PQ=1,1W(175MHz)	2a	Fui	BFQ42, BFR98, BFS51, BLW18, BLY61
2SC845	Si-N	VHF-Tr/E, 55V, 0,4A, PQ=1,4W(100MHz)	2a	Fui	BFS23, BLY34
2SC646	Si-N			Nec	—
2SC647	Si-N	Uni, 30V, 0,2A, 0,35W, 70MHz	2a	Fui	BC168, BC183, BC238, BC548, 2SD787++
2SC648	Si-N	=2SC647: ra, 60MHz	2a		BC169, BC164, BC239, BC549, 2SC2675+
2SC649	Si-N	S, 30V, 0,3A, 0,35W, 60MHz	2a	Fui	BC337..338, 2SC1827, 2SC2002..03, ++
2SC85	Ge-N	S, 25V, 0,4A, 0,12W, -/700ns	2a	Mit	ASY73..75
2SC850	Si-N	=2SC649: 50V, 0,5A, 70MHz	2a	Fui	BC337, 2SC1827, 2SC2002..03, 2SC3377, ++
2SC651	Si-N	AM/FM-L, 50V, 8A, PQ=40W(50MHz)	23a	Nec	—
2SC852	Si-N	VHF/UHF, 45V, 0,08A, 0,5W, 1500MHz	5q	Nec	BFR36, BFW16, 2SC2852
2SC853	Si-N	Uni, 70V, 0,2A, 0,4W, 100MHz	7c"	Nec, Mic	BC639, 2SC3665, 2SD867, 2SD1226, ++
2SC854	Si-N	VHF-Tr/E, 40V, 0,3A, PQ=0,75W(175MHz)	2a	Fui	BFR98, BFS51, BFX55, BLW16, BLY81
2SC855	Si-N	VHF-Tr/E, 40V, 0,4A, PQ=0,9W(175MHz)	2a	Fui	BFR98, BFS51, BFX55, BLW16, BLY61
2SC856	Si-N	Vid, 150V, 0,05A, 0,3W, 150MHz	2a	Hit	BF297..299, BF422A, 2SC3467..68, ++
2SC857(H,K)	Si-N	S/Vid, 200V, 0,05A, 0,2W, 100MHz	2a	Hit	BF298..299, BF422A, 2SC3467..88, ++
2SC658(FP)	Si-N	Uni, ra, 20V, 0,05A, 0,1W, 140MHz	7c	Say, Mic	BC169, BC184, BC239, BC549, 2SC2875+
2SC859(FP)	Si-N	Uni, ra, 20V, 0,05A, 0,1W, 140MHz	7c	Say	BC169, BC164, BC239, BC549, 2SC2675+
2SC88	Ge-N	S, 25V, 0,4A, 0,12W, -/600ns	2a	Mit	ASY73..75
2SC860	Si-N	VHF/UHF, 15V, 0,03A, 700MHz	5q	Say	BF377..378, BF689, BF763, 2N2857, ++
2SC881	Si-N	S-L, 450/250V, 1A, 50W, 7MHz	23a	Hit	BU128, BUW71, BUX45, 2SC1463, ++
2SC862	Si-N	S-L, 650/250V, 5A, 50W, 7MHz	23a	Hit	BU326(A), BU426(A), BUX97(A,B), ++
2SC863	Si-N	VHF/ZF, 60V, 25mA, 600MHz	5k	Tos	BF198..199, BF224..225, BF310..311, ++
2SC864	Si-N	VHF/ZF, 40V, 25mA, 600MHz	5k	Tos	BF198..199, BF224..225, BF310..311, ++
2SC885	Si-N	AM-L, 80V, 2A, PQ=4,5W(50MHz)	2a	Fui	—
2SC868	Si-N	AM-L, 80V, 1,5A, PQ=3,5W(27MHz)	43m	Fui	(2SC1306, 2SC1909, 2SC2078, 2SC2092, ++)
2SC867	Si-N	S-L, 400/150V, 1A, 23W, 8MHz	22a	Son	BUW40(A,B), TIP46, 2SC1316, 2SD859A, ++
2SC867A	Si-N	=2SC867: 520V, 3A, 48W	22a		BUT93, TIP75C, 2SC2826, 2SC3038, ++
2SC888	Si-N	S/Vid, 130/40V, 0,03A, 0,2W, 150MHz	7b	Mit	BF297..299, BF422, 2SC2375, 2SC3467, +

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2SC869	Si-N	=2SC868: 160V	7b		BF297..299, BF422, BF463, 2SC3467,++
2SC87	Si-N	HF/S, 30V, 0,1A, 0,6W, 250MHz	2a	Fui	BFW16..17, BFX55
2SC870	Si-N	Uni, ra, 30V, 0,03A, 0,2W, 150MHz	7b	Mit	BC169, BC184, BC239, BC549, 2SC2675+
2SC671	Si-N	Uni, ra, 30V, 0,03A, 0,2W, 150MHz	7b		BC169, BC184, BC239, BC549, 2SC2675+
2SC672(M)	Si-N	UHF-Tr/E, 40V, 0,4A, PQ=1,3W(400MHz)	2a	Fui	BFS50, MRF629, 2N3946, 2SC2852
2SC873	Si-N	Uni, 75V, 1A, 0,5W, 200MHz	2a	Say	BC140..141, BSX45..47, 2N1990,++
2SC874	Si-N	=2SC873: 50V	2a	Say	BC140..141, BSX45..47, 2N1990,++
2SC675	Si-N	Uni, 75V, 0,2A, 0,5W, 170MHz	2a	Say, Mic	BC140..141, BC300..301, 2N1711,++
2SC676	Si-N	=2SC875: 50V	2a	Say, Mic	BC140..141, BC300..302, 2N3053,++
2SC677	Si-N	S, 40V, 0,2A, 0,3W, <20/35ns	2a	old	BSS11, BSX19..20, 2N2368..69(A),++
2SC878	Si-N	=2SC877: <12/22ns	2a	old	BSS11, BSX19..20, 2N2368..69(A),++
2SC879	Si-N	S, 60V, 1A, 0,8W, <70/100ns	2a	old	BSS13, BSS27, BSV77, 2N5189,++
2SC88	Si-N	=2SC87: 120V	2a		BC300, BF257, BSY55..56, 2N1693(A),++
2SC880	Si-N	S, 60V, 1A, 0,6W	2a	old	BSS13, BSS27, BSV77, 2N5169,++
2SC861	Si-N	NF-E, Uni, 60V, 0,2A, 0,4W, 150MHz	7c*	Nec, Mic	BC337A, BC637, 2SC3377, 2SC3939,++
2SC882	Si-N	S-L, 150/100V, 2A, 25W, 30MHz	23a	old	—
2SC863	Si-N	S-L, 90/70V, 2A, 25W, 30MHz	23a	old	—
2SC684	Si-N	NF/S-L, 60V, 2A, 15W, 30MHz	22a	old	BDV10..12, 2N4233, 2SC3252
2SC685	Si-N	S-L, 330/100V, 7A, 50W, -/<9µs	23a	old	BU104, BU606..608, BUX18(A..C),++
2SC866	Si-N	=2SC885: 270/90V	23a	old	BU104, BU608..608, BUX18(A..C),++
2SC887	Si-N	=2SC865: 210/60V	23a	old	BU104, BU606..608, BUX18(A..C),++
2SC888	Si-N	=2SC685: 150/70V	23a	old	BU104, BU606..608, BUW86..87,++
2SC869	Si-N	=2SC885: 90/60V	23a	old	BU104, BU606..608, BUW66..87,++
2SC89(H)	Ge-N	S, 25V, 0,4A, 0,12W, -/380ns	2a	Hit	ASY73..75
2SC890	Si-N	UHF-Tr/E, 40V, 0,4A, PQ=1,3W(500MHz)	2a	Nec	BFS50, MRF629, 2N3946
2SC891	Si-N	UHF-L, 40V, 0,6A, PQ=4W(500MHz)	55s	Nec	(BLW43, BLW60, 2N5945)
2SC892	Si-N	UHF-L, 40V, 1,2A, PQ=8W(500MHz)	55s	Nec	(BLU97, BLX68, BLY53)
2SC693	Si-N	NF/HF/S-L, 100V, 0,5A, 12W, 20MHz	43m	Fui	(BD139, BD230, 2SD1382, 2SD1563)
2SC694	Si-N	Uni, 25V, 0,1A, 0,1W, 200MHz	10b	Son	BC168, BC183, BC238, BC548, 2SD767
2SC895	Si-N	NF/S-L, 150/90V, 2,5A, 23W, 20MHz	22a	Son	BD241D, 2SD608(A), 2SD772(A,B), 2SD1138
2SC696	Si-N	Uni, 55V, 0,2A, 0,3W, 200MHz	2a	Nec	BC167, BC182, BC237, BC547, 2SD767++
2SC897	Si-N	NF/S-L, 150/90V, 7A, 60W, 15MHz	23a	Hit	BD245D, 2N3442, 2SD551, 2SD732, 2SD1046
2SC898	Si-N	=2SC897: 150/110V, 80W	23a	Hit	BD245D, 2N3442, 2SD551, 2SD732, 2SD1046
2SC899	Si-N	Uni, ra, 50V, 0,05A, 0,25W, 250MHz	7c	Nec	BC194, BC414, BC550, 2SC1775(A),++
2SC90(H)	Ge-N	S, 25V, 0,4A, 0,12W, -/380ns	2a	Hit	ASY73..75
2SC900	Si-N	Uni, ra, 30V, 0,02A, 0,25W, 100MHz	7c	Nec, Mic	BC169, BC184, BC239, BC549, 2SC2675+
2SC901	Si-N	S-L, TV-HA, 200V, 5A, 50W, 50MHz	23a	Mat	BU104, BU606..608, 2SD1154
2SC901A	Si-N	=2SC901: 250V	23a		BU104, BU608..608, 2SD1154
2SC902	Si-N	S-L, 150/80V, 10A, 75W, -/<4µs	23a	Fui	BDW12, 2SD551, 2SD733, 2SD1047,++
2SC903	Si-N	Uni, 35V, 0,3A, 0,2W, 150MHz	7b	Mit	BC337, BC635, 2SC3377, 2SC3939,++
2SC904	Si-N	=2SC903: 50V	7b	Mit	BC637, 2SD667, 2SC3377, 2SC3939,++
2SC905	Si-N	=2SC903: 85V	7b	Mit	BC637, 2SD667, 2SD1226, 2SD1485,++
2SC908	Si-N	Uni, 50V, 0,5A, 0,6W, 70MHz	2a*	Fui	BC337, BC637, 2SC3377, 2SC3939,++
2SC907(H)	Si-N	Uni, 40V, 0,1A, 0,2W, 240MHz	2a	Hit	BC167, BC163, BC237, BC547, 2SD767++
2SC907A(AH)	Si-N	=2SC907: 60(AH=70)V	2a		BC174, BC182, BC190, BC546, 2SC3245+
2SC908	Si-N	UHF-Tr/E, 40V, 0,5A, PQ=1,2W(500MHz)	2a	Mit	BFS50, MRF629, 2N3948
2SC909	Si-N	UHF-L, 40V, 0,5A, PQ=3,5W(500MHz)	55r	Mit	BLW43, BLW60, 2N5945
2SC91(H)	Ge-N	S, 25V, 0,4A, 0,12W, -/360ns	2a	Hit	ASY73..75
2SC910	Si-N	UHF-L, 40V, 1A	55r	Mit	BLU97, BLX68, BLY53
2SC911(A)	Si-N	UHF-Tr/E, 40V, 0,5A, PQ=1,4W(500MHz)	51r	Mit	BLX68
2SC912(M)	Si-N	Uni/S, 70V, 0,4A, 0,15W, <25/140ns	5c	Mit	BSW41, BSY63, 2N4123, 2N2221..22,++
2SC913	Si-N	S, 40V, 0,3A, 0,3W, <45/42ns	2a	Fui, Hit, Nec	BSS10, BSX19..20, BSX26, 2N3261,++
2SC913	Si-N			Oki	—
2SC914(A)	Si-N	=2SC913: <80/88ns	2a	=2SC913	BSS10, BSX19..20, BSX26, 2N3261,++
2SC915(A)	Si-N	=2SC913: 30V	2a	=2SC913	BSS10, BSX19..20, BSX26, 2N3261,++
2SC916	Si-N	S-L, 100/70V, 1,5A, <63/160ns	2a	Fui, Nec, Oki	(BD139, BD230, BD379, 2SD1177..78,++)
2SC917	Si-N	TV-ZF-E, 40V, 0,05A, 550MHz	5q	Hit	BF199, BF224, BF311, BF373, BF597++
2SC916	Si-N	VHF, 20V, 0,03A, 400MHz	5q	Son	BF225, BF310, BF314, 2SC1393..94,++
2SC919	Si-N			Nec	—
2SC92	Si-N	FM/VHF-L, 100V, 2A, PQ=9W(100MHz)	2a	Nec	—
2SC920	Si-N	AM/FM-VM/O, 50V, 0,03A, 250MHz	24b	Nec	BF240..241, BF254..255, BC594..595,++
2SC921	Si-N	FM-VM/D, 25V, 0,01A, 650MHz	24b	Nec	BF225, BF310, BF314, 2SC1393..94,++
2SC922	Si-N	AM/FM, ra, 30V, 0,02A, >400MHz	7c	Nec, Mic	BF241, BF255, BF310, BF314, 2SC829++
2SC923	Si-N	Uni, 40V, 0,1A, 0,25W, 100MHz	7c	Nec, Mic	BC167, BC163, BC237, BC547, 2SC3112+
2SC924	Si-N	NF, AM-ZF, 30V, 0,05A, 0,25W, 250MHz	7c	Nec	BF240..241, BF254..255, BF594..595,++
2SC925	Si-N	Uni, 30V, 0,05A, 0,25W, 250MHz	7c	Nec	BC188, BC183, BC238, BC548, 2SC2390+

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2SC926(A-4,A-5)	Si-N	Vid, 115. 210V, 0,03..0,1A, 0,1..0,25W	10b	Son	BF298..299, BF422, BF483, 2SC3468, ++
2SC927	Si-N	VHF-ra, 30V, 0,02A, ZF, 500MHz	5q	Say	BF225, BF310, BF314, BF502, 2SC1856+
2SC928	Si-N	VHF-ra, 30V, 0,02A, ZF, 500MHz	5q	Say	BF225, BF310, BF314, BF502, 2SC1856+
2SC929(NP,SPA)	Si-N	HF-ra, AM-V, 15 30V, 0,03A, 300MHz	≈7c,7c	Say, Mic	BF240, BF254, BF494, BF594, 2SC829++
2SC93	Si-N	=2SC92: 80V	2a	Nec	—
2SC930(NP,SP)	Si-N	FM, 15..30V, 0,03A, 300MHz	≈7c,7c	Say, Mic	BF241, BF255, BF495, BF595, 2SC829++
2SC931	Si-N	NF/HF/S-L, 50V, 3A, 10W, 120MHz		Say	(BD785, BDX35, MJE240..242, 2SC3252)
2SC932	Si-N	=2SC931: 30V		Say	(BD765, BDX35, MJE240..242, 2SC3252)
2SC933	Si-N	Uni/S, 50V, 0,3A, 0,2W, 500MHz	5q	Say, Mic	BSV59, BSW41, BSY63, 2N2221..22, ++
2SC933NP,SPA	Si-N	=2SC933: 0,3W	7c		→2SC933
2SC934	Si-N	=2SC933: 20V	5q	Say, Mic	BSV59, BSW41, BSY63, 2N2221..22, ++
2SC934NP,SPA	Si-N	=2SC934: 0,3W	7c		→2SC934
2SC935	Si-N	TV-S-L, 300/300V, 2,5A, 50W, 5MHz	23a	Hit	BU104, BU126, BU806..608, 2SD1154
2SC936(A)	Si-N	TV-VA, 1000/500(A=600)V, 1A, 22W, 7MHz	23a	Hit	BU204..206, 2SC1101, 2SC1167, 2SD1095
2SC937	Si-N	TV-HA, 1200/500V, 2,5A, 22W, 4MHz	23a	Hit	BU204. 206, 2SC1132, 2SD1097..1096, ++
2SC936	Si-N	Uni, 80V, 0,2A, 0,25W, 100MHz	7c	Nec, Mic	BC337A, BC637, 2SC3939, 2SD1226, ++
2SC939	Si-N	AMP, 150/130V, 15A, 50W, 20MHz	23a	Nec	BU104, BU606..606, 2SD916
2SC94	Si-N	=2SC92	2a	Nec	—
2SC940	Si-N	=2SC939: 200V, 9A	23a	Nec	BU108, BU109, BU124(A)
2SC941(TM)	Si-N	HF, 35V, 0,02A, 0,2W, 120MHz	7c	Tos	BF240..241, BF254..255, BF594..595, ++
2SC942	Si-N-Darl	Dual, 20V, 0,02A, 0,6W, 700MHz	TO-100	Fui	—
2SC943	Si-N	Uni, 80V, 0,2A, 0,3W, 220MHz	2a	Nec	BC174, BC162, BC190, BC546, 2N3904++
2SC944(S)	Si-N	Uni, 80V, 0,1A, 0,25W, 250MHz, 20/300ns	7c	Nec	BC174, BC162, BC190, BC546, 2N3904++
2SC945(T)	Si-N	Uni, 80V, 0,1A, 0,25W, 250MHz	7c	Nec, Mic	BC174, BC182, BC190, BC546, 2SD767++
2SC945L	Si-N	≈2SC945: ra	7c		2SC1775(A), 2SC2674..75, 2SC3376, ++
2SC946	Si-N			Nec	—
2SC947(Z)	Si-N	VHF/UHF, 25V, 15mA, 650MHz	5q	Mat, Mic	BF377..378, BF689, BF763, 2N2657, ++
2SC946(Z)	Si-N	VHF/UHF, 25V, 15mA, 600MHz	5q	Mat, Mic	BF377..376, BF689, BF763, 2N2657, ++
2SC949	Si-N	Uni, ra, 45V, 0,05A, 0,2W, 200MHz	7c	Njr	BC184, BC413..414, BC550, 2SC2390, ++
2SC95	Si-N	Vid, 140V, 0,1A, 0,8W, 140MHz	2a	Tos	BF257..259, BF657..659, 2N5058..59
2SC950	Si-N	Uni, 30V, 0,1A, 0,3W, 100MHz	7c	Njr	BC168, BC163, BC238, BC548, 2SD767++
2SC951	Si-N	=2SC950: 80V	7c	Njr	BC174, BC182, BC190, BC546, 2SD767++
2SC952	Si-N	=2SC950: 100V	7c	Njr	2SC2240, 2SC2459, 2SC3245(A), 2SC3248, ++
2SC953	Si-N	Uni, 30V, 0,2A, 0,6W, 90MHz	8a	Njr	BC337. 338, BC835, BC637, 2SC3377, ++
2SC954	Si-N	Uni, 80V, 0,4A, 0,6W, 90MHz	8a	Njr	BC337A, BC637, 2SC3939, 2SD1226, ++
2SC955	Si-N	Uni, 20V, 0,05A, 0,15W, 150MHz	8a	Njr	BC168, BC163, BC236, BC546, 2SC1890+
2SC956	Si-N	Uni, 50V, 0,05A, 0,15W, 200MHz	6a	Njr	BC167, BC182, BC237, BC547, 2SC1690+
2SC957	Si-N	VHF, 30V, 0,1A, 0,36W, 700MHz	2a	Son	BF225, BF310, BF311, BF502, 2SC1856++
2SC956	Si-N			Nec	—
2SC959(S)	Si-N	Uni, 120V, 0,7A, 0,7W, 100MHz	2a	Nec, Mic	BC300, BSY55..56, 2N1893(A), 2N2102, ++
2SC96	Si-N	Dual, 25V, 0,15A, 0,5W, 150MHz	TO-77	Tos	(2N3409..3411, 2N3728..3729)
2SC960(S)	Si-N	=2SC959:	43m	Nec	(2SC2384, 2SC2690(A), 2SD1362)
2SC961	Si-N	NF/S-L, 120/90V, 7A, 80W, 13MHz	23a	old	BD245C, BD550, 2N5633, 2SD1046, ++
2SC962	Si-N	=2SC961: 100/80V	23a	old	BD245C, BDV95, BDX95, 2N5632..33, ++
2SC963	Si-N	Uni, 35V, 0,05A, 0,25W, 200MHz, B=70	2a	Fui	BC168, BC163, BC236, BC546, 2SC1680+
2SC964	Si-N	=2SC963: B=100	2a	Fui	BC168, BC183, BC238, BC546, 2SC1890
2SC965	Si-N	=2SC963: 45V, -/<300ns	2a	Fui	BC167, BC182, BC237, BC547, 2N3904++
2SC966	Si-N	Uni, 30V, 0,2A, 0,5W, 70MHz	2a	Fui	BC337..338, BC635, BC637, 2SC3377, ++
2SC967	Si-N	Uni, 30V, 0,5A, 0,5W, 70MHz	2a	Fui	BC337..338, BC635, BC637, 2SC3377, ++
2SC968	Si-N	Uni, 50V, 0,5A, 0,5W, 70MHz	2a	Fui	BC337, BC637, 2SC3939, 2SD1226, ++
2SC968	Si-N	Uni, 50V, 0,2A, 0,5W, 60MHz	2a	Fui	BC337, BC637, 2SC3377, 2SD1226, ++
2SC97	Si-N	S, 60V, 1A, 0,8W, 250MHz, <50/150ns	2a	Nec	BSS13, BSV77, 2N2218..19, 2N5189, ++
2SC970	Si-N	Uni, 50V, 0,5A, 0,5W, 70MHz	2a	Fui	BC337, BC637, 2SC3939, 2SD1226, ++
2SC971	Si-N	Uni, 50V, 0,5A, 1W, 70MHz	2a*	Fui	BC337, BC637, BC639, 2SD1225..26, ++
2SC972	Si-N	Uni, 70V, 0,4A, 0,6W, 80MHz	2a	Say	BC140..141, BC300..301, 2N1711, ++
2SC973(A)	Si-N	UHF-Tr/E, 40V, 0,5A, PQ=4W(500MHz)	55r	Mit	BLW43, BLW60, 2N5945
2SC974	Si-N	UHF-Tr/E, 40V, 1A, PQ=6W(500MHz)	55r	Mit	BLU97, BLX68, BLY53
2SC975(A)	Si-N	UHF-Tr/E, 35V, 1,5A, PQ=8W(500MHz)	55r	Mit	BLW44, BLW61, 2N5946
2SC976	Si-N	UHF-Tr/E, 55V, 0,4A, PQ=1,1W(1GHz)	55r	Mit	BFT99, BLV91, MRF617
2SC977	Si-N	UHF-Tr/E, 55V, 0,6A, PQ=3W(1GHz)	55r	Mit	BLU99
2SC976	Si-N	UHF-Tr/E, 55V, 1,2A, PQ=5,5W(1GHz)	55r	Mit	—
2SC979	Si-N	Uni, 70V, 0,1A, 0,3W, 250MHz, 25/430ns	2a	Tos	BC174, BC182, BC190, BC546, 2N2222A+
2SC979A	Si-N	=2SC979: 100V	2a		2SC2240, 2SC2459, 2SC3245(A), 2SC3246, ++
2SC97A	Si-N	=2SC97: 80V, <30/90ns	2a		BSV95, BSW39, 2N3735
2SC96	Si-N	SS, 20V, 0,1A, 0,3W, 350MHz, B>30	2a	Mat	BSV99..92, BSX92..93, 2N2368..69(A), ++
2SC960(G,GTM)	Si-N	Uni, 70V, 0,1A, 0,2W, 400MHz, 25/630ns	7c	Tos	BC174, BC182, BC190, BC546, 2N2222A+

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2SC980A(G,GTM)	Si-N	=2SC980: 90V	7c		2SC2240, 2SC2459, 2SC3245(A), 2SC3248,++
2SC981	Si-N	NF/S-L, 100V, 5A, 25W, 10MHz	22a	Tos	BD243C, BD543C, BD953, 2SD613,++
2SC982(TM)	Si-N-Darl	NF/S, 40V, 0,3A, 0,4W, B>5000	7c(C)	Tos	BC517, BC617, MPS-A25..29
2SC982(TM)	Si-N-Darl				—
2SC983	Si-N	Vid, 250/150V, 0,05A, 0,8W, 120MHz	9b	Tos	BF298..299, BF422, BF483, 2SC3468,++
2SC984	Si-N	Uni, 50V, 0,5A, 0,35W, 230MHz	2a	Hit	BC337, BC637, 2SC3939, 2SD1226,++
2SC984H	Si-N	=2SC984: 100V	2a		BC639, BCX24, 2SC4414, 2SD667, 2SD1226
2SC985(A)	Si-N	UHF, ra, 20V, 0,04A, 3,2GHz	51s	Nec	BFQ59..60, BFQ70..71, BFT97, 2N5762
2SC986	Si-N	UHF-Tr/E, 35V, 0,2A, 2,5GHz	55r	Nec	BFT98, BFQ68
2SC987(A)	Si-N	UHF, 20V, 0,03A, 4,5GHz	51s	Nec	BFQ69, BFQ71, BFQ85, BFR14, BFR91
2SC988(A, B)	Si-N	UHF, ra, 20V, 0,03A, 3GHz	5q	Nec	BFR15, BFT66..67, BFS55, 2N5650..52
2SC989	Si-N	UHF, 20V, 0,05A, 3GHz	24d	Nec	BFT65, BFQ72
2SC99	Si-N	=2SC98: B>40	2a	Mat	BSV89..92, BSX92..93, 2N2368..69(A),++
2SC990	Si-N	UHF-L, 50V, 2A, PQ=13,4W(400MHz)	55s	Nec	BLW94, BLX94, MRF323
2SC991	Si-N	VHF-Tr/E, 36V, 0,4A, PQ=1,3W(175MHz)	2a	Tos	BFQ42, BFS51, BFR98, BLW18, BLY61
2SC992	Si-N	VHF-Tr/E, 36V, 0,6A, PQ=2,5W(175MHz)	2a	Tos	BFS22, BFW46, BLY33, MRF237, 2N3924
2SC993	Si-N	Uni, 25V, 0,2A, 0,2W, 400MHz	2a	Fui	BSW41, BSY82..83, 2N706A, 2N4124,++
2SC994	Si-N	VHF-O/Tr, 36V, 0,1A, PQ>0,95W(175MHz)	2a	Tos	BFW16..17, BFX55
2SC995	Si-N	Vid, 300/300V, 0,15A, 0,8W, 100MHz	2a	Tos	BF259, BF659, BFR59, BFS69, 2N5058
2SC996	Si-N	=2SC995:	43a	Tos	(BF417, BF459, BF617, BF758,++)
2SC997	Si-N	HF/ZF, 40V, 25mA, 600MHz	5k	Tos	BF198..199, BF224..225, BF310..311,++
2SC998	Si-N	VHF-Tr/E, 40V, 0,4A, PQ>1W(175MHz)	2a	Tos	BFQ42, BFS51, BFR98, BLW18, BLY61
2SC999	Si-N	TV-HA, 1500/700V, 1,5A, 50W, 1MHz	23a	Tos	BU204..206, 2SD575, 2SD818
2SC999A	Si-N	=2SC999: 1500/650V, 2,5A, 4MHz	23a		BU204..206, 2SD575, 2SD818
2SD					2SD
2SD100	Ge-N	NF-Tr, 32V, 0,4A, 0,25W	2a	Tos	AC127, AC176, AC137, 2SD72, 2SD352
2SD1000	Si-N	SMD, Uni, 80V, 0,7A, 110MHz	39b	Nec	BCX58, 2SC2331, 2SD1005..07, 2SD1413,++
2SD1001	Si-N	SMD, Uni, 30V, 0,3A, 140MHz	39b	Nec	2SC2332, 2SC3433, 2SD375, 2SD963(A)
2SD1002	Si-N	SMD, Uni, 45V, 1A, 180MHz	39b	Nec	BCX54..58, 2SC3444, 2SD374A, 2SD1363,++
2SD1003	Si-N	=2SD1002: 80V	39b	Nec	BCX55..56, 2SC3444, 2SD374A, 2SD1363,++
2SD1004	Si-N	=2SD1002: 100V	39b	Nec	BCX56, 2SD1005, 2SD1363, 2SD1413..19
2SD1005	Si-N	SMD, 100V, 1A, 100MHz	39b	Nec	BCX58, 2SC2331, 2SD1363, 2SD1413..19
2SD1006	Si-N	SMD, 100V, 0,7A, 90MHz	39b	Nec	BCX58, 2SC2331, 2SD1363, 2SD1413..19
2SD1007	Si-N	=2SD1006: 120V	39b	Nec	2SC2331, 2SD1413..19
2SD1009	Si-N	SMD, Uni, ra, 150/150V, 0,05A, 160MHz	39b	Mat	—
2SD100A	Ge-N	=2SD100: 45V	2a		—
2SD101	Ge-N	NF-Tr, 30V, 0,6A, 0,25W	2a	Tos	—
2SD1010	Si-N	hi-Ueb, hi-beta, ra, 50V, 0,05A, 200MHz	7c	Mat	2SC3495, 2SC3071, (2SC3112..13)
2SD1011	Si-N	hi-Ueb, hi-beta, ra, 100V, 0,02A, 200MHz	7c		2SC3495, 2SC3071
2SD1012	Si-N	lo-sat, 20V, 0,7A, 0,25W, 250MHz	40c	Say	2SD1207, 2SD1816, 2SD1335
2SD1014	Si-N	S, 50/50/50V, 2A, 0,9W, B>150	7c(9mm)	Son	—
2SD1015	Si-N	S, 140/50/50V, 2A, 0,9W, B>150	7c(9mm)	Son	—
2SD1016	Si-N	TV-HA, 1500/600V, 7A, 50W	23a	Say	BU503A, 2SC3027..28, 2SC3636, 2SD322,++
2SD1017	Si-N	TV-Reg, 250V, 2A, 50W	16j	Nec	TIP51..55, 2SC2309
2SD1018	Si-N	=2SD1017: 4A, 30W	16j	Nec	TIP51..54, 2SC2624, 2SC3083
2SD102	Si-N	NF/S-L, 110V, 3A, 25W, 1MHz, 3/10µs	22a	Tos	BD241C, BD243C, BD539D, BD939,++
2SD1020	Si-N	Uni, lo-sat, 30V, 0,7A, 0,35W, 170MHz	40c	Nec	2SC4433, 2SC4435, 2SD1207, 2SD1816
2SD1021	Si-N	Uni, 30V, 1A, 0,35W, 100MHz	40c	Nec	BC337..337, BC635, BC637, BC639,++
2SD1022	Si-N-Darl	S-L, 100/100V, 5A, 30W, B>1500	17c(A)	Shi	BD849, BD901, BDW23C, BDW63C,++
2SD1023	Si-N-Darl+Di	S-L, 100/100V, 5A, 30W, B>1500	17c(A)	Shi	BU306, 2SD1025
2SD1024	Si-N-Darl	S-L, 100/100V, 8A, 50W, B>1500	17c(A)	Shi	BD849, BD901, BDW23C, BDW63C,++
2SD1025	Si-N-Darl+Di	S-L, 200/200V, 8A, 50W, B>1500	22c(E)	Shi	2SD1141, 2SD1756
2SD1026	Si-N-Darl+Di	S-L, 100/100V, 15A, 100W, B>1500	82c(E)	Shi	BDV67A, BDW33C, 2SD1296, 2SD1299,++
2SD1027	Si-N-Darl+Di	S-L, 200/200V, 15A, 100W, B>1500	82c(E)	Shi	2SD1515
2SD1029	Si-N	NF/S-L, 80V, 4A, 40W	17j	Say	BD243A, BD539A, BD535, BD949,++
2SD1029K	Si-N	=2SD1029: 100V	17j		BD243B, BD539B, BD537, BD951,++
2SD103	Si-N	=2SD102: 30V	22a	Tos	BD241B, BD243B, BD539B, BD937,++
2SD1030	Si-N	=2SD1010: SMD	35a	Mat	2SC3639
2SD1031	Si-N-Darl	NF/S-L, 120V, 6A, 50W, B=4000	17c(A)	Sak	BD851, BDT21, BDW73D, BDX53D,++
2SD1032	Si-N	NF/S-L, 80V, 4A, 80W, 0,2/1,4µs	13j	Mat	BD245A, BDV91, 2SC2631, 2SD395..396,++
2SD1032A	Si-N	=2SD1032: 30V	13j		BD245B, BDV93, 2SC2631, 2SD395..396,++
2SD1032B	Si-N	=2SD1032: 100V	13j		BD245C, BDV95, 2SC2631, 2SD395..396,++
2SD1033	Si-N	Vid-E, 200/150V, 2A, 20W, 10MHz	30j	Nec	2SD1557, (2SD810, 2SD1133, 2SD1250(A))
2SD1034(A)	Si-N-Darl	S-L, 600/450V, 300A, 1250W, B=300		Tos	—
2SD1035	Si-N	S-L, 150/120/100V, 3A, 40W, 1,5MHz	17j	Fui	—
2SD1036	Si-N	S-L, 150/120/100V, 15A, 150W, 1,5MHz	20j	Fui	—

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2SD1037	Si-N	S-L, 150/120/100V, 30A, 180W, 1,5MHz	20j	Fui	—
2SD1038	Si-N	S-L, 150/120/100V, 40A, 180W, 1,5MHz	20j	Fui	—
2SD1039	Si-N	=2SD1035:	22a	Fui	—
2SD104	Ge-N	NF, 20V, 0,4A, 0,15W, B>60	2a	Tos	AC127, AC178, AC137, 2SD72, 2SD352
2SD1040(A)	Si-N	=2SD1036: 120W	23a	Fui	—
2SD1041	Si-N	=2SD1037: 200W	23a	Fui	—
2SD1042	Si-N	=2SD1033.	23a	Fui	—
2SD1043	Si-N-Darl+Di	S-L, 430V, 5A, 80W, B=1000	23a	Mat	BU322(A), BU921..922, 2SD1461, ++
2SD1044	Si-N-Darl+Di	S-L, 100V, 8A, 60W, B>700	77c (E)	Mat	TIP142, 2SD1170, 2SD1230
2SD1044A	Si-N-Darl+Di	=2SD1044: 170V	77c (E)		2SD921, 2SD1090, 2SD1122..1123
2SD1045	Si-N	Uni, 30V, 3A, 0,9W, 200MHz	7c(9mm)	Hit	2SD1347, 2SD1507, 2SD1617, 2SD1864
2SD1046	Si-N	NF/S-L, 150V, 8A, 80W, 15MHz	18j	Say	BD245D, 2SC2837, 2SC3263, 2SD751, ++
2SD1047	Si-N	NF/S-L, 160V, 12A100W, 15MHz	18j	Say	BD745F, 2SC3263
2SD1048	Si-N	=2SD1012: SMD	35a	Say	BCW65..68
2SD1049	Si-N	NF/S-L, 120V, 25A, 80W	18j	Fjd	BD249C
2SD105	Ge-N	=2SD104: B>35	2a	Tos	AC127, AC176, AC187, 2SD72, 2SD352
2SD1050	Si-N-Darl+Di	NF/S-L, 100V, 10A60W, B>1000	20j	Hit	2SD851..852, 2SD1087, 2SD1129
2SD1051	Si-N	Uni, 50V, 1,5A, 1W, 150MHz	9c	Mat	MPS650..651, 2SC3328, 2SD819, 2SD1207++
2SD1052	Si-N	NF/S-L, hi-beta, 50V, 3A30W, B>250	17j	Tos	2SC1983, 2SD1943
2SD1052A	Si-N	=2SD1052: B>400	17j		2SC1983, 2SD1943
2SD1053	Si-N	S-L, 400V, 1A, 15W	30j	Nec	2SC3362..3363, 2SC3632, (BD410)
2SD1054	Si-N	S-L, 300/250V, 3A, 60W	23a	Hit	BU126, TIP51..54, 2SC1463, 2SD832
2SD1055	Si-N	Uni, 40V, 2A, 0,75W, 100MHz	9c	Rhm	MPS650, 2SC3328, 2SD1207, 2SD1227, ++
2SD1056	Si-N-Darl	S-L, 600/600V, 50A, 400W, B>100	≈74	Fjd	—
2SD1059	Si-N	NF/S-L, 100V, 6A, 40W	17j	Say	BD243C, BD543C, BD601, 2SD550, ++
2SD1060	Si-N	lo-sat, 60V, 5A, 30W, 30MHz	17j	Say	2SC3253, 2SC3258, 2SD12361
2SD1061	Si-N	lo-sat, 60V, 7A, 40W, 10MHz	17j	Say	2SC3254, 2SD12371
2SD1062	Si-N	lo-sat, 60V, 12A, 40W, 10MHz	17j	Say	2SC3345, 2SD1212
2SD1063	Si-N	lo-sat, 60V, 7A, 60W, 10MHz	18j	Say	2SD1187
2SD1064	Si-N	lo-sat, 60V, 12A, 80W, 10MHz	18j	Say	2SD12381
2SD1065	Si-N	lo-sat, 60V, 15A, 90W, 10MHz	18j	Say	2SD1840
2SD1066	Si-N-Darl	S-L, 600/600V, 100A, 770W, B>100		Fjd	—
2SD1067	Si-N-Darl	S-L, 600/600, 30A, 200W, B=200	≈74	Fjd	—
2SD1068	Si-N	S-L, TV-HA, 1000V, 10mA, 25W, 8,5MHz	17j	Son	2SC4256, 2SC4451
2SD1069	Si-N	300/150V, 7A, 40W, 18MHz	17c	Tos	BU406..408, 2SC3589..91, 2SD1163(A)++
2SD107	Si-N-Darl	NF/S-L, 80/60V, 5A50W, B>1000	23a	Tos	BDX63A, MJ1001, 2N6056, 2SD1124, ++
2SD1070	Si-N	NF/S-L, 100V, 10A, 60W	16j	Nec	BD245C, BD545C, BDV95, 2SC2681, ++
2SD1071	Si-N-Darl	S-Reg, 450/450V, 6A, 40W, B>500	17j	Fjd	BU910..912, 2SD798..99, 2SD1245
2SD1072	Si-N-Darl	S-Reg, 450/450V, 5A, 60W, B>500	17j	Fjd	BU911..912, 2SD978, 2SD987, 2SD1245, ++
2SD1073	Si-N-Darl	S-L, 300/250V, 4A, 40W, B>1000	17j	Fjd	BU910..912, 2SD816, 2SD978, 2SD987, ++
2SD1074	Si-N	NF/S-L, 120V, 1A, 10W, B=160	30j	Hit	2SC2983, 2SC4134, 2SD1283..84, 2SD1220++
2SD1075	Si-N	=2SD1074; B=100	30j	Hit	2SC2963, 2SC4134, 2SD1283..84, 2SD1220++
2SD1076	Si-N	NF/S-L, 25V, 2,5A, 20W	30j	Hit	2SC3073, 2SC3386, 2SD1221, 2SD1802, ++
2SD1077L,S	Si-N	=2SD1076: 35V	30j	Hit	2SC3073, 2SC3386, 2SD1221, 2SD1602, ++
2SD1078	Si-N	NF/S-L, 50V, 2A, 20W	30j	Hit	2SC3076, 2SD1261..1282, 2SD1601, ++
2SD1079	Si-N	=2SD1078: 60V	30j	Hit	2SC3388, 2SD1281..82, 2SD1815..18
2SD108	Si-N-Darl	=2SD107: 80/40V	23a	Tos	BDX63A, MJ1001, 2N6056, 2SD1124, ++
2SD1080L,S	Si-N	NF/S-L, 180/120V, 1,5A, 20W	30j	Hit	2SC4027, 2SD1033, 2SD1557
2SD1081L,S	Si-N	=2SD1080: 180/180V	30j	Hit	2SC4027, 2SD1033, 2SD1557
2SD1082	Si-N	=2SD1080: 200/160V	30j	Hit	2SD1033, 2SD1557
2SD1083L,S	Si-N	NF/S-L, TV, 150V, 2A, 10W, B>150	30j	Hit	2SD1033, 2SD1557
2SD1084	Si-N-Darl	S-L, 500/400V, 50A, 400W, B=300	≈74	Hit	—
2SD1085	Si-N-Darl+Di	Z-Di(B→C), 300/300V, 3A, 40W, B=3000	17j	Hit	2SD816, 2SD1073, (BU806..607)
2SD1087	Si-N-Darl+Di	NF/S-L, 100V, 15A, 100W, B=3000	20j	Tos	2SD829, 2SD852, 2SD1129..1130
2SD1088	Si-N-Darl	S-L, 300/250V, 6A, 30W, B=5000	17j	Tos	BU910..912, 2SD835, 2SD1114, 2SD1307, ++
2SD1089	Si-N-Darl	S-L, 350/350V, 6A, 30W, B=1000	17j	Tos	BU910..912, 2SD835, 2SD1114, 2SD1307, ++
2SD1090	Si-N	TV-Reg, hi-beta, 200V, 5A, 80W, B>500	18j	Tos	—
2SD1091	Si-N-Darl+Di	NF/S-L, 170V, 4A, 40W, B=5000	17j	Mat	2SC3186, 2SD930, 2SD1023, 2SD1121
2SD1092	Si-N	TV-Reg, hi-beta, 55V, 4A, 80W, B>500	18j	Tos	2SC2825
2SD1093	Si-N	TV-SN, 1000/400V, 7A, 50W, <5/11µs	23a	Hit	BU536, BU545, BU902..903
2SD1094	Si-N	TV-SN, 1000/400V, 10A, 50W, <5/21µs	23a	Hit	BU628A
2SD1095	Si-N	TV-HA, 1200V, 1,5A, 50W	23a	Hit	BU204..206, 2SD1097, 2SC1132, 2SC1167++
2SD1096	Si-N	NF/S-L, 25V, 1A, 10W	30j	Hit	2SD1078..79, 2SD1295, 2SD1601
2SD1097	Si-N	TV-HA, 1200V, 2,5A, 50W	23a	Hit	BU204..206, 2SC1132, 2SC1922, 2SD818, ++
2SD1098	Si-N	TV-HA, 1200V, 3A, 50W	23a	Hit	BU207..209(A), 2SC1875, 2SD850, ++
2SD1099	Si-N	TV-HA, 1200V, 5A, 50W	23a	Hit	BU207..209(A), 2SC2928, 2SD954, ++

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2SD11	Ge-N	S, 25V, 0,3A, 0,15W, 2,5MHz	2a	Nec	ASY73..75
2SD110	Si-N	NF/S-L, 130V, 10A, 100W, 1MHz, 3/12µs	23a	Tos	BDX11, 2N3442, 2SD551, 2SD732..733, ++
2SD1100	Si-N	NF-Tr/E, 20V, 2A, 0,9W, B=400	7c(9mm)	Hit	2SC3225, 2SC4389, 2SD1014, 2SD1146
2SD1101	Si-N	SMD, Uni, 25V, 0,7A	35a	Hit	BCW65..66
2SD1102	Si-N	TV-HA, 1200V, 4A, 50W	23a	Hit	BU207..209(A), 2SC1358, 2SD1495, ++
2SD1103	Si-N	TV-HA, 1200V, 5A, 50W	23a	Hit	BU207..209(A), 2SC2928, 2SD954, ++
2SD1104	Si-N	TV-HA, 1200V, 6A, 50W	23a	Hit	BU508(A), 2SC3025..3026, 2SD821, ++
2SD1105	Si-N	NF/S-L, 120V, 15A, 200W, 1MHz	23a	Mat	BDW10, 2N5630..31, 2SC1584, 2SD752, ++
2SD1106	Si-N-Darl	S-L, 450/450V, 50A, 400W, B=300	≈74	Nec	—
2SD1107	Si-N-Darl	S-L, 500/500V, 50A, 400W, B=300	≈74	Nec	—
2SD1109	Si-N	NF/S-L, 100/100V, 6A, 70W	16j	Nec	BD245C, BDV95, 2SC2681, 2SC2837, ++
2SD1109A	Si-N	=2SD1109: 120/120V	16j		BD245C, 2SC2681, 2SC2706, 2SC2837, ++
2SD111	Si-N	=2SD110: 100V	23a	Tos	BD317, BDW21C, BDY53, 2N5832..33, ++
2SD1110	Si-N	NF/S-L, 120/120V, 7A, 80W, 15MHz	16j	Nec	BD245C, 2SC2661, 2SC2706, 2SC2837, ++
2SD1110A	Si-N	=2SD1110: 130/130V	16j		BD245D, 2SC2706, 2SD731, 2SD1046, ++
2SD1111	Si-N-Darl	Uni, 80V, 0,7A, 0,6, B=25000	7c	Say	BC618, BC877, BC879, BSR51..52
2SD1112	Si-N	S-L, 300/300V, 0,2A, 10W, 70MHz	30j	Mat	2SC3129, 2SC3588, 2SC3805, 2SC4003, ++
2SD1113	Si-N-Darl+Di	int.Z-Diode, 300/300V, 6A, 40W, B>500	17j	Hit	(2SD971, 2SD991, 2SD1071, 2SD1068..89++)
2SD1114	Si-N-Darl+Di	S-L, 400/300V, 5A, 50W, B>500	17j	Hit	BU910..912, 2SD835, 2SD1245
2SD1115	Si-N-Darl+Di	S-L, 400/300V, 3A, 40W, B>500	17j	Hit	2SD977..978, 2SD987, 2SD1072
2SD1116	Si-N-Darl	S-L, 400/300V, 3A, 40W, B>500	17j	Hit	2SD977..978, 2SD987, 2SD1072
2SD1117	Si-N	NF/S-L, 40V, 10A, 50W	17j	Fjd	BD705, BD743, BD805, BD905, ++
2SD1117A	Si-N	=2SD1117: 80V	17j		BD709, BD743B, BD809, BD909, ++
2SD1118	Si-N-Darl	NF/S-L, 80V, 10A, 50W, B>300, <1/5µs	17j	Fjd	BDT63A, BDT65A, BDW93B, BDX33B, ++
2SD1119	Si-N	SMD, Uni, 40V, 3A, 150MHz	39b	Mat	2SC4521, 2SD1624
2SD1120	Si-N-Darl	NF/S-L, 200/150V, 2A, 40W, B=1000	17j	Mat	2SC3166, 2SD930, 2SD1023, 2SD1121
2SD1121	Si-N-Darl	NF/S-L, 200/200V, 3A, 50W, B=1000	17j	Mat	2SC3166, 2SD930, 2SD1023, 2SD1025
2SD1122	Si-N-Darl	NF/S-L, 200/150V, 5A, 80W, B=1000	18j	Mat	2SD921, 2SD1090, 2SD1123
2SD1123	Si-N-Darl	NF/S-L, 200/150A, 100W, B=1000	16j	Mat	—
2SD1124	Si-N-Darl	NF/S-L, 80V, 6A, 80W, B=1000	18j	Mat	BDV65A..C, TIP141..142
2SD1125	Si-N-Darl	NF/S-L, 80V, 12A, 100W, B=1000	16j	Mat	BDV65A..C, BDV67A..D, BDW83B..D, ++
2SD1126	Si-N-Darl+Di	NF/S-L, 120/120V, 10A, 50W, B>1000	17j	Hit	BDT63C, BDT65C, BDX33D, 2SD1807, ++
2SD1127	Si-N-Darl+Di	NF/S-L, 120V, 10A, 50W, B>1000	17j	Hit	BDT63C, BDT65C, BDX33D, 2SD1807, ++
2SD1128	Si-N-Darl	NF/S-L, 150/100V, 5A, 30W, B=5000	17j	Fjd	BDX53F, 2SD830, 2SD1189, 2SD1590
2SD1129	Si-N-Darl	NF/S-L, 100V, 15A, 100W, B>1000	20j	Hit	2SD829, 2SD852
2SD113	Si-N	NF/S-L, 100V, 30A, 200W, 1,5MHz, 3/10µs	23a	Tos	BDW30, BDY29, MJ802, 2SD797
2SD1130	Si-N-Darl	NF/S-L, 100V, 20A, 100W, B>1000	20j	Hit	—
2SD1131	Si-N	NF/S-L, 50V, 4A, 40W, 8MHz	17j	Hit	BD243A, BD535, BD539A, BD949, ++
2SD1132	Si-N	=2SD1131: 80V	17j	Hit	BD243A, BD535, BD539A, BD949, ++
2SD1133	Si-N	NF/S-L, 70/50V, 4A, 40W, 7MHz	17j	Hit	BD243A, BD537, BD539B, BD951, ++
2SD1134	Si-N	=2SD1133: 70/80V	17j	Hit	BD243A, BD537, BD539B, BD951, ++
2SD1135	Si-N	NF/S-L, 100V, 4A, 40W, 10MHz	17j	Hit	BD243C, BD539C, BD953, 2SD712, ++
2SD1136	Si-N	HV, 700/400V, 4A, 30W	17c	Hit	BU406..406, 2SD623, 2SD1150, 2SD1159, ++
2SD1137	Si-N	TV-VA, 100V, 4A, 40W	17j	Hit	BD243C, BD539C, BD953, 2SD712, ++
2SD1136	Si-N	NF/S-L, TV-VA, 200/150V, 2A, 30W	17j	Hit	BD239F, 2SC2660, 2SD810, 2SD780
2SD1139	Si-N	NF/S-L, 200/150V, 2A, 30W	17j	Hit	BD239F, 2SC2660, 2SD810, 2SD780
2SD114	Si-N	=2SD113: 70V	23a	Tos	BDW30, BDY29, MJ802, 2SD797
2SD1140	Si-N-Darl	Uni, 30V, 1,5A, 0,9W, B=7000	7c(9mm)	Tos	2SD1536, 2SD1786, 2SD1661, 2SD2046, ++
2SD1141	Si-N-Darl+Di	S-L, 400/300V, 6A, 40W, B=3000	17j	Hit	BU910..912, 2SD835, 2SD1114, 2SD1245
2SD1142	Si-N	TV-HA, 1500/1500V, 3,5A, 50W	23a	Nec	BU208(A), BU506(A), 2SD849..850, ++
2SD1143	Si-N	TV-HA, 1500/1500V, 5A, 50W	23a	Nec	BU208(A), BU508(A), 2SC2928, 2SD954, ++
2SD1145	Si-N	Tr, lo-sat, 80V, 5A, 0,9W, 120MHz	7c(9mm)	Say	2SC4462, 2SD2243
2SD1146	Si-N	NF-Tr/E, 50V, 2A, 0,9W, B=300	7c(9mm)	Son	2SC3328, 2SC4145, 2SD1207, 2SD2162
2SD1147	Si-N-Darl	NF/S-L, 120V, 5A, 30W, B=5000	17j	Fjd	BD651, BDT21, BDW63D, BDW73D, ++
2SD1148	Si-N	HiFi-NF-E, 140/140V, 10A, 100W	18j	Tos	BD245D, 2SC2706, 2SC2987(A), 2SD1047
2SD1149	Si-N	=2SD1011: SMD	35a	Mat	2SC3951
2SD1150	Si-N	AMP, 350/90V, 6A, 40W	17c	Say	BU406, BU406, 2SC3175, 2SC3591, ++
2SD1151	Si-N+Di	TV-HA, 1500V, 5A, 95W, B=40..150	23a	Mat	—
2SD1152	Si-N	Uni, 55V, 0,1A, 0,2W	7c	Hit	BC167, BC162, BC237, BC547, ++
2SD1153	Si-N-Darl	Uni, 50V, 1,5A, 0,9W, B>4000	7c(9mm)(C)	Say	2SD1579, 2SD1978, 2SD1981, 2SD2067
2SD1154	Si-N	HV, TV-HA, 800/325V, 7A, 50W	23a	Mat	BU104, BU606, BU608
2SD1155	Si-N-Darl	S-L, 400/400V, 50A, 300W, B=400	≈74	Fjd	—
2SD1158	Si-N	S-L, 100/80V, 5A, 58W	49m	Mit	2N5002, 2N5004, 2N5284 5265
2SD1157	Si-N	NF/S-L, hi-beta, 80V, 4A, 25W, B=400	17j	Fjd	2SC2315..16, 2SC2491
2SD1158	Si-N	NF/S-L, hi-beta, 80V, 6A, 40W, B=400	17j	Fjd	2SC4024, 2SD1947
2SD1159	Si-N	AMP, 200/60V, 4,5A, 40W, 10MHz	17c	Say	BU406..408, 2SC3189, 2SC3589, 2SD1163++

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2SD116	Si-N	NF/S-L, 100V, 7A, 75W	23a	Fui	BD245C, BDV95, BDX85, 2N5632..33, ++
2SD1160	Si-N+Di	S-L, TV, Rbe=800Ω, Io-sat, 50V, 2A, 10W	30j	Tos	—
2SD1161	Si-N+R	SMD, Emitter-R≈130Ω, Uni, 30V, 0,03A	35a	Say	—
2SD1162	Si-N-Darl	S-L, 500V, 5A, 40W, B>400, 1/18µs	17j	Nec	BU922T
2SD1163	Si-N	HV, 700/400V, 12A, 40W	17c	Hit	BU406..406, 2SC3173, 2SC3590, ++
2SD1163A	Si-N	=2SD1163: 350/150V	17j		BU406..406, 2SC3175, 2SC3591, ++
2SD1164	Si-N-Darl+Di	NF/S-L, 150V, ±1,5A, 10W, B>2000	30j	Nec	2SC4339, (2SD985..986)
2SD1165(A)	Si-N-Darl	S-L, 1000/900V, 100A, 1250W, B=150		Nec	—
2SD1166	Si-N-Darl	S-L, 1000/900V, 200A, 2500W, B=150		Tos	—
2SD1168	Si-N	S-L, TV-HA, 1500/800V, 5A, 50W	23a	Mat	BU208A, BU508(A), 2SC2928, 2SD954, ++
2SD1169	Si-N-Darl	NF/S-L, 150/80V, 5A, 40W, B=10000	22c(A)	Mat	(2SD1128)
2SD117	Si-N	=2SD116: 150V	23a	Fui	BD245D, BDX11, 2N3442, 2SD551, 2SD732, ++
2SD1170	Si-N-Darl	NF/S-L, 100V, 10A, 70W, B=4000	77c(E)	Sak	2SD921, 2SD923, 2SD1090, 2SD1210, ++
2SD1171	Si-N+Di+Rbe≈27	TV-HA, 1500V, 5A, 50W	23a	Mat	BU206D, BU508D, 2SC3481..82, 2SC3681 ++
2SD1172	Si-N+Di+Rbe≈27	TV-HA, 1500V, 5A, 65W	23a	Mat	BU206D, BU508D, 2SC3481..82, 2SC3681 ++
2SD1173	Si-N+Di+Rbe≈27	TV-HA, 1500V, 5A, 70W	23a	Mat	BU508D, 2SC3481..82, 2SC3681, 2SD953, ++
2SD1174	Si-N+Di+Rbe≈27	TV-HA, 1500V, 5A, 95W	23a	Mat	BU508D, 2SC3481..82, 2SC3681, 2SD953, ++
2SD1175	Si-N+Di+Rbe≈27	TV-HA, 1500V, 5A, 100W	23a	Mat	BU508D, 2SD953, 2SC3481..82, 2SC3681, ++
2SD1176	Si-N-Darl+Di	NF/S-L, 100V, 8A, 45W, B=4000	17c(A)	Mat	BD645, BD897, BDW73A, BDX53A, ++
2SD1176A	Si-N-Darl+Di	=2SD1176: 80V	17c(A)		BD647, BD899, BDW73B, BDX53B, ++
2SD1177	Si-N	NF-L, TV-VA, 100/60V, 2A, 20W, 230MHz	14h	Hit	BD379, BD791, BDX35, MJE243..244
2SD1178	Si-N	=2SD1177: 100/80V	14h	Hit	BD379, BD791, BDX35, MJE243..244
2SD1179	Si-N	NF/S-L, TV-VA, 120/100V, 1,5A, 20W	14h	Hit	2SC2481, 2SC2690(A), 2SC3117, 2SD669
2SD118	Si-N	NF/S-L, 130V, 7A, 100W, 2MHz	23a	Tos	BD245D, BDX11, 2N3442, 2SD551, 2SD732, ++
2SD1180	Si-N	=2SD1179: 120/110V	14h	Hit	2SC2481, 2SC2690(A), 2SC3117, 2SD669
2SD1181	Si-N	NF/S-L, 180V, 1,5A, 10W	17n	Hit	(2SC2238A,B, 2SC2344, 2SD608A, 2SD1138+)
2SD1182	Si-N	=2SD1181: 50W	17n	Hit	(2SC2660, 2SD780, 2SD772A,B,++)
2SD1183	Si-N	TV-SN, 1200/800V, 3A, 50W, <2/11µs	23a	Hit	BU546, BU903, 2SC1875, 2SD1098, ++
2SD1184	Si-N	TV-SN, 1500/800V, 3A, 50W, <2/11µs	23a	Hit	BU208(A), BU508(A), BU908, 2SC3023, ++
2SD1185	Si-N	TV-SN, 1200/800V, 5A, 50W, <2/11µs	23a	Hit	BU546, BU903, 2SD1099, 2SD1103, ++
2SD1186	Si-N	TV-SN, 1200/800V, 5A, 50W, <2/11µs	23a	Hit	BU208(A), BU508(A), BU908, 2SC2928, ++
2SD1187	Si-N	NF/S-L, Io-sat, 100/80V, 10A, 80W	18j	Tos	2SD1840
2SD1188	Si-N				—
2SD1189	Si-N	NF-L, 40V, 2A, 5W, 100MHz	14b	Rhm	2SD1682..1863
2SD119	Si-N	=2SD118: 100V	23a	Tos	BDW21C, BDX95, 2N3055, 2N5632..33, ++
2SD1190	Si-N-Darl+Di	NF/S-L, 70V, 4A, 30W, 20MHz, B=5000	17c(A)	Say	BD717, BDW23B, BDW53B, BDW63B, ++
2SD1191	Si-N-Darl+Di	=2SD1190: 7A	17c(A)	Say	BD647, BD899, BDW73B, BDX53B, ++
2SD1192	Si-N-Darl+Di	=2SD1190: 10A	17c(A)	Say	BDT63A, BDT65A, BDW93B, BDX33B, ++
2SD1193	Si-N-Darl+Di	=2SD1190: 15A	16c(A)	Say	BDV67A, BDW63B, 2SD1026
2SD1194	Si-N-Darl+Di	NF/S-L, 110V, 3A, 30W, 20MHz, B=4000	17c(A)	Say	BDW53D, BDW63D, 2SD1091, 2SD1147, ++
2SD1195	Si-N-Darl+Di	=2SD1194: 5A	17c(A)	Say	BD651, BDT21, BDW63D, 2SD1147, ++
2SD1196	Si-N-Darl+Di	=2SD1194: 8A	17c(A)	Say	BD651, BDT21, BDW73D, BDX53D, ++
2SD1197	Si-N-Darl+Di	=2SD1194: 10A	16c(A)	Say	BDV65C, BDV67B, BDW83D, 2SD1296, ++
2SD1198	Si-N-Darl	Uni, 30V, 1A, 1W, 150MHz, B>4000	9c	Mat	BC817..818, BC875, BSR50..52, ++
2SD1198A	Si-N-Darl	=2SD1198: 80V	9c		BC818, BC875, BSR50..52, 2SD893A, ++
2SD1199	Si-N	=2SD1010: 0,4W	9c	Mat	→2SD1010
2SD12	Si-N	NF/S-L, 75V, 2,5A, 60W	23a	Mat	BD245B, BDV93, 2N4915, 2SD895..896, ++
2SD120	Si-N	NF/S, 80V, 1,5A, 1W, 750/470ns	2a	Hit	BCX40, BSX45..47, 2N5320..21, ++
2SD1200(F)	Si-N	NF/S-L, 80V, 0,7A, 5W, 120MHz	14b	Rhm	2SC3421, (BD139, BD230, 2SD1378, ++)
2SD1201	Si-N	S-L, 850/400V, 10A, 100W, B>200	23a	Hit	BU323A, BU922, BUW81(A), 2SD685, ++
2SD1202	Si-N	S-L, 50/40V, 8A, 100W, B=100	30c	Hit	BU323A, BU922, BUW81(A), 2SD685, ++
2SD1203	Si-N	S-L, 850/400V, 15A, 100W, B>200	23a	Hit	BU932, 2SD572..573, 2SD711(A), ++
2SD1204	Si-N	S-L, 80/40V, 15A, 100W, B=100	23a	Hit	BU932, 2SD572..573, 2SD711(A), ++
2SD1205	Si-N-Darl	=2SD892:	9c	Mat	→2SD892
2SD1205A	Si-N-Darl	=2SD892A:	9c		→2SD892A
2SD1206	Si-N	hi-Ueb, 30V, 0,1A, 0,4W, 150MHz	9c	Mat	2SD889, 2SD1208, 2SD1807, (BC548, ++)
2SD1207	Si-N	Uni, Io-sat, 80V, 2A, 1W, 150MHz	7c(9mm)	Say	2SC3328, 2SC4145, 2SD2069, 2SD2485
2SD1208	Si-N-Darl	int. Z-Di, 45V, 5A, 100W, B=2k..20k	16c(J)	Tos	BDX83B, TIP142, 2SD828..629, ++
2SD1209	Si-N-Darl	Uni, 80V, 1A, 0,9W, B>4000	7c(9mm)	Hit	2SD1153, 2SD1660, 2SD1809, 2SD1981, ++
2SD121	Si-N	=2SD120: 100V	2a	Hit	BCX40, BSS15, BSX48..47, 2N5320, ++
2SD1210	Si-N-Darl+Di	NF/S-L, 150V, ±10A, 80W, B>1000	16j	Nec	BDV67D, 2SD1123, 2SD1296, 2SD1299
2SD1211	Si-N	Uni, 120V, 0,5A, 1W, 200MHz	7c(9mm)	Mat	2SC2235, 2SD687(A), 2SD1812, 2SD1937, ++
2SD1212	Si-N	S-L, Io-sat, 80V, 12A, 35W, 120MHz	17j	Say	2SC3345..48, 2SD1062
2SD1213	Si-N	S-L, Io-sat, 80V, 20A, 50W, 120MHz	18j	Say	2SD1841
2SD1214	Si-N-Darl+Di	NF/S-L, 25V, 2A, 35W, B=5000	17j	Mat	BD713, BDW23, BDW53, BDW63, ++
2SD1215	Si-N-Darl+Di	NF/S-L, 25V, 4A, 40W, B=5000	17j	Mat	BD713, BDW23, BDW53, BDW63, ++

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2SD1216	Si-N-Darl+Di	NF/S-L, 25V, 8A, 45W, B=5000	17j	Mat	BD643, BD895, BDW73, BDX53, ++
2SD1217	Si-N-Darl+Di	NF/S-L, 50V, 2A, 35W, B=5000	17c(H)	Mat	BD715, BDW23A, BDW53A, BDW63A, ++
2SD1218	Si-N-Darl+Di	NF/S-L, 50V, 4A, 40W, B=5000	17c(H)	Mat	BD715, BDW23A, BDW53A, BDW63A, ++
2SD1219	Si-N-Darl+Di	NF/S-L, 50V, 3A, 45W, B=5000	15c(I)	Mat	BD645, BD897, BDW73A, BDX53A, ++
2SD122	Si-N	NF/S-L, 60V, 3A, 15W	2a	Hit	(BD241A, BD535, BD935, 2SD712, ++)
2SD1220	Si-N	TV-NF-E, 150V, 1,5A, 10W, 100MHz	30j	Tos	2SC4027, 2SD1033, 2SD1080 .82, 2SD1918++
2SD1221	Si-N	NF/S-L, 60V, 3A, 20W, 3MHz	30j	Tos	2SC3386, 2SC3518, 2SC3592, 2SD1602, ++
2SD1222	Si-N-Darl+Di	NF/S-L, 60V, 3A, 15W, B=5000	30c(A)	Tos	2SD1520, 2SD1817, 2SD1955
2SD1223	Si-N-Darl+Di	NF/S-L, 100V, 4A, 15W, B=5000	30c(A)	Tos	2SC4339, 2SD1520, 2SD1955
2SD1224	Si-N-Darl	NF/S-L, 30V, 1,5A, 10W, B=10000	30j	Tos	2SC3132, 2SD1222, 2SD1759, 2SD1799, ++
2SD1225(M)	Si-N	NF-Tr/E, 40V, 1A, 1W, 150MHz	9c	Rhm	BC635, BC637, BC639, 2SD667, ++
2SD1226(M)	Si-N	NF-Tr/E, 80V, 0,7A, 1W, 120MHz	9c	Rhm	BC639, 2SC2235, 2SC2383, 2SD667, ++
2SD1227(M)	Si-N	NF-Tr/E, 40V, 2A, 1W, 100MHz	9c	Rhm	MRS650..651, 2SC3328, 2SD1146, 2SD1207
2SD1228(M)	Si-N	NF-Tr/E, 50V, 0,5A, 0,6W, 250MHz	9c	Rhm	BC337, BC635, BC637, BC639, ++
2SD1229	Si-N-Darl+Di	NF/S-L, 70V, 10A, 60W, B=5000	16c(A)	Say	BDV65A, BDW83B, TIP141, 2SD1125, ++
2SD123	Si-N	=2SD122: 100V	2a	Hit	(BD241C, BD539C, BD939, 2SD712, ++)
2SD1230	Si-N-Darl+Di	NF/S-L, 110V, 8A, 60W, B=4000	16c(A)	Say	BDV65C, 2SD1210
2SD1231	Si-N-Darl+Di	NF/S-L, 70V, 10A, 70W, B=5000	23a(A)	Say	BDV65A, BDX83B, BDX85B, MJ3001, ++
2SD1232	Si-N-Darl+Di	NF/S-L, 70V, 15A, 80W, B=5000	23a(A)	Say	BDV67A, BDW83B, BDX67A, MJ4034, ++
2SD1233	Si-N-Darl+Di	NF/S-L, 110V, 8A, 70W, B=4000	23a(A)	Say	BDV65C, BDX63C, BDX65C, 2SD922, ++
2SD1234	Si-N-Darl+Di	NF/S-L, 110V, 10A, 60W, B=4000	23a(A)	Say	BDV65C, BDW83D, BDX65C, 2SD922, ++
2SD1235	Si-N	NF/S-L, Io-sat, 60V, 8A, 30W, 120MHz	17j	Say	2SC3254..3255
2SD1236	Si-N	=2SD1236L: 120V	17j	Say	—
2SD1236L	Si-N	NF/S-L, Io-sat, 90V, 5A, 30W, 20MHz	17j	Say	2SC3258
2SD1237	Si-N	=2SD1237L: 120V	17j	Say	—
2SD1237L	Si-N	NF/S-L, Io-sat, 90V, 7A, 40W	17j	Say	—
2SD1238	Si-N	=2SD1238L: 120V	17j	Say	—
2SD1238L	Si-N	NF/S-L, Io-sat, 120V, 12A, 80W, 20MHz	18j	Say	2SD1840
2SD1239	Si-N	NF/S-L, 120V, 20A, 100W	23a	Say	BC249C, BD745D, 2SD1049
2SD124	Si-N	NF/S-L, 60V, 6A, 60W, 1,6/7,2µs	23a	Hit	BD245A, BDV91, BDX91, 2N5873..74, ++
2SD1240	Si-N	NF/S-L, 120V, 25A, 120W	23a	Say	BC249C
2SD1241	Si-N	NF/S-L, 60V, 5A, 60W	18j	Mat	BD245A, BDV91, 2SC2681, 2SD895..896, ++
2SD1241A	Si-N	=2SD1241: 60V	18j		BD245B, BDV93, 2SC2681, 2SD695 896, ++
2SD1242	Si-N	NF/S-L, 60V, 8A, 70W	18j	Mat	BD245A, BDV91, 2SC2681, 2SD695..896, ++
2SD1242A	Si-N	=2SD1242: 60V	18j		BD245B, BDV93, 2SC2681, 2SD895..896, ++
2SD1243	Si-N	NF/S-L, 60V, 10A, 100W	18j	Mat	BD245A, BD545A, BDV91, 2SC2681, ++
2SD1243A	Si-N	=2SD1243: 60V	18j		BD245B, BD545B, BDV93, 2SC2681, ++
2SD1244	Si-N	=2SD965: 1W	9c	Mat	→2SD965
2SD1245	Si-N-Darl+Di	S-L, 500/400V, 8A, 40W, B>500	17c	Mat	BU810, BU912, 2SD798 .799, ++
2SD1246	Si-N	NF-Tr/E, Io-sat, 30V, 2A, 0,75W	7c	Say	2SC4484, 2SD1207, 2SD2177
2SD1247	Si-N	=2SD1246: 2,5A, 1W	7c(9mm)	Say	2SC4467, 2SD1347
2SD1248	Si-N-Darl+Di	NF/S-L, 120V, 8A, 40W, B>1000	17c(A)	Hit	BD651, BDT21, BDW73D, BDX53D, ++
2SD1249	Si-N	NF/S-L, 350/250V, 0,75A, 35W, 30MHz	30j	Mat	(BUW40(A, B), TIP47..50, 2SD859(A), ++)
2SD1249A	Si-N	=2SD1249: 400V	30j		(BUW40(A,B), TIP48..50, 2SD859A, ++)
2SD124A	Si-N	=2SD124: 75V, 7A	23a		FBD245B, BDV93, BDX93, 2N5874, ++
2SD125	Si-N	NF/S-L, 100V, 8A, 60W, 1,6/7,7µs	23a	Hit	BD245C, BDV95, BDX95, 2N5632..33, ++
2SD1250(A)	Si-N	NF/S-L, 200V, 2A, 30W, 20MHz	30j	Mat	(2SD1033, 2SC2660, 2SD760, 2SD1138, ++)
2SD1251	Si-N	NF/S-L, 60V, 4A, 30W, 1MHz	30j	Mat	2SD1904, 2SD1906, (BD241A, BD535, ++)
2SD1251A	Si-N	=2SD1251: 80V	30j		2SD1906, 2SD2200, (BD241B, BD537, ++)
2SD1252	Si-N	NF/S-L, 60V, 3A, 35W, 30MHz	30j	Mat	2SD190203, (BD241A, BD535, BD935, +)
2SD1252A	Si-N	=2SD1252: 80V	30j		2SD1906, 2SD2200, (BD241B, BD537, ++)
2SD1253	Si-N	NF/S-L, 60V, 4A, 40W, 20MHz	30j	Mat	2SD1904, 2SD2198, (BD243A, BD535, ++)
2SD1253A	Si-N	=2SD1253: 60V	30j		2SD1906, 2SD2200, (BD243B, BD537, ++)
2SD1254	Si-N	NF/S-L, Io-sat, 130V, 3A, 30W, 30MHz	30j	Mat	2SD1529
2SD1255	Si-N	NF/S-L, Io-sat, 130V, 4A, 35W, 30MHz	30j	Mat	—
2SD1256	Si-N	NF/S-L, Io-sat, 130V, 5A, 40W, 30MHz	30j	Mat	—
2SD1257	Si-N	NF/S-L, Io-sat, 130V, 7A, 40W, 30MHz	30j	Mat	—
2SD1257A	Si-N	=2SD1257: 150V	30j		—
2SD1258	Si-N	hi-beta, 200V, 1A, 40W, 25MHz, B>500	30j	Mat	—
2SD1259	Si-N	hi-beta, 60V, 3A, 40W, 50MHz, B>500	30j	Mat	—
2SD1259A	Si-N	=2SD1259: 100V	30j		—
2SD125A	Si-N	=2SD125: 7A	23a		BD245C, BDV95, BDX95, 2N5832..33, ++
2SD126	Si-N	NF/S-L, 150V 8A, 60W, 1,6/8,2µs	23a	Hit	BD245D, BDX11, 2N3442, 2SD551, 2SD732, ++
2SD1260	Si-N-Darl+Di	NF/S-L, 60V, 2A, 35W, 20MHz, B>1000	14b(A)	Mat	(BD715, BDW23A, BDW53A, 2SD837, ++)
2SD1260A	Si-N-Darl+Di	=2SD1260: 60V	14b(A)		(BD717, BDW23B, BDW53B, 2SD837A, ++)
2SD1261	Si-N-Darl+Di	NF/S-L, 60V, 4A, 40W, 20MHz, B>1000	14b(A)	Mat	(BD715, BDW23A, BDW53A, 2SD637, ++)

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2SD1261A	Si-N-Darl+Di	=2SD1261: 80V	14b(A)		(BD717, BDW23B, BDW53B, 2SD837A,++)
2SD1262	Si-N-Darl+Di	NF/S-L, 80V, 8A, 45W, 20MHz, B>1000	14b(A)	Mat	(BD645, BD897, BDW73A, BDX53A,++)
2SD1262A	Si-N-Darl+Di	=2SD1262: 80V	14b(A)		(BD647, BD899, BDW73B, BDX53B,++)
2SD1263	Si-N	NF/S-L, 350/250V, 0,75A, 35W, 30MHz	17c	Mat	2SC3969, (BUW40(A,B), TIP47..50)
2SD1263A	Si-N	=2SD1263: 400/300V	17c		2SC3969, (BUW40(A,B), TIP48..50)
2SD1264(A)	Si-N	=2SD1250(A):	17c	Mat	2SC3298B, 2SC4382, 2SD1587, 2SD2337
2SD1265(A)	Si-N	=2SD1251:	17c	Mat	BD951F, 2SC3851, 2SD1408, 2SD2000
2SD1266(A)	Si-N	=2SD1252(A):	17c	Mat	BDT31F, 2SC3851, 2SD1408, 2SD2000
2SD1267(A)	Si-N	=2SD1253(A):	17c	Mat	BD951F, 2SC3851, 2SD1408, 2SD2000
2SD1268	Si-N	=2SD1254:	17c	Mat	—
2SD1269	Si-N	=2SD1255:	17c	Mat	—
2SD127	Ge-N	NF-Tr/E, 23V, 0,5A, 0,25W	2a	Son	AC127, AC176, AC187, 2SD72, 2SD352
2SD1270	Si-N	=2SD1258:	17c	Mat	—
2SD1271(A)	Si-N	=2SD1257(A):	17c	Mat	—
2SD1272	Si-N	=2SD1258:	17c	Mat	(2SC2317)
2SD1273	Si-N	=2SD1259:	17c	Mat	2SD1944, (2SD1943, 2SC1983)
2SD1273A	Si-N	=2SD1259A:	17c		2SD2092
2SD1274	Si-N	NF/S-L, 150/80V, 5A, 40W, 40MHz	17c	Mat	2SC3566, 2SC4334, 2SD772(A,B)
2SD1274A	Si-N	=2SD1274: 200/80V	17c		2SC4153, (BD243F, 2SD772A,B)
2SD1274B	Si-N	=2SD1274: 250/80V	17c		(2SD772B)
2SD1275	Si-N-Darl+Di	=2SD1260:	17c(A)	Mat	BDT61F, 2SD1790, 2SD1825, 2SD1987
2SD1275A	Si-N-Darl+Di	=2SD1260A:	17c(A)		BDT61AF, 2SD1414, 2SD1788, 2SD1933
2SD1276	Si-N-Darl+Di	=2SD1261:	17c(A)	Mat	BDT61F, 2SD1790, 2SD1825, 2SD1987
2SD1276A	Si-N-Darl+Di	=2SD1261A:	17c(A)		BDT61AF, 2SD1414, 2SD1788, 2SD1933
2SD1277	Si-N-Darl+Di	=2SD1262:	17c(A)	Mat	BD643F, BDT63F, 2SD1416, 2SD1826..27
2SD1277A	Si-N-Darl+Di	=2SD1262A:	17c(A)		BD645F, BDT63AF, 2SC4062, 2SD141516
2SD1278	Si-N	S-L, 1200/650V, 8A, 100W, <1/5µs	23a	Mat	BU508(A), 2SC3412, 2SD905..906, 2SD1498
2SD1279	Si-N	TV-HA, 1400V, 10A, 50W, 3MHz	23a	Tos	2SC3888
2SD128	Ge-N	=2SD127: 32V	2a	Son	AC127, AC176, AC187, 2SD72, 2SD352
2SD1260	Si-N	SMD, Uni, 20V, 1A, 150MHz	39b	Mat	BC688, BCX5458, BCX68, 2SC2884, ++
2SD1261	Si-N	NF/S-L, 100V, 2A, 20W	30j	Hit	2SC4135, 2SD1557, 2SD1815..16
2SD1262	Si-N	NF/S-L, 100V, 2A, 20W	30j	Hit	2SC4135, 2SD1557, 2SD1815..16
2SD1283	Si-N	NF/S-L, 120V, 2A, 20W	30j	Hit	2SC4135, 2SD1557, 2SD1815..16
2SD1264	Si-N	NF/S-L, 120V, 2A, 20W	30j	Hit	2SC4135, 2SD1557, 2SD1815..16
2SD1266(Z)	Si-N-Darl+Di	NF/S-L, 80V, ±1A, 8W, B=2k..30k	30c	Nec	2SC2871, 2SD1598, 2SD1800
2SD1287	Si-N-Darl	S-L, 300/250V, 30A, 150W, B=300	23a(G)	Hit	BUT13, MJ10022..10023
2SD1288	Si-N	NF/S-L, 120V, 7A, 70W, 55MHz	16j	Nec	BD245C, BD545D, 2SD718, 2SD1046, ++
2SD1289	Si-N	NF/S-L, 120V, 8A, 60W, 60MHz	16j	Nec	BD245C, BD545D, 2SD718, 2SD1046, ++
2SD129	Si-N	NF/S-L, 90V, 3A, 25W, 1MHz	22a	Tos	BD241B, BD939, 2N4233, 2SD712, ++
2SD1290	Si-N+Di+Rbe=50	TV-HA, 1500V, 3A, 50W	16c	Mat	BU508D, 2SC3479, 2SC3481..3482
2SD1291	Si-N+Di+Rbe=50	TV-HA, 1500V, 3A, 50W	16c	Mat	BU508D, 2SC3479, 2SC3461..3482
2SD1292	Si-N	NF-Tr/E, 120V, 1A, 0,9W, 100MHz	7c(9mm)	Rhm	2SC2383, 2SC3228, 2SD667(A), 2SD1812, ++
2SD1293(M)	Si-N	=2SD1292: 1W	9c	Rhm	2SC2383, 2SC3228, 2N3700..01, 2SD667
2SD1294	Si-N-Darl	int.Z-Di(B→C) 60V, 5A, 60W, B=2k..20k	18c(J)	Tos	BDV65, TIP140..142, 2SD1124, 2SD1170
2SD1295	Si-N	NF/S-L, 50V, 1,5A, 20W, 150MHz	30j	Mat	2SC3076, 2SD1078, 2SD1281..1264, ++
2SD1298	Si-N-Darl+Di	NF/S-L, 150V, ±15A, 100W, B=1k..30k	16j	Nec	BDV67D, 2SD1027, 2SD1299, 2SD1515
2SD1297	Si-N-Darl+Di	NF/S-L, 150V, 25A, 100W, B=1k..30k	16j	Nec	—
2SD1298	Si-N-Darl+Di	S-L, 500/400V, ±10A, 100W, B=2002000	16j	Nec	2SC3262, 2SD979
2SD1299	Si-N-Darl+Di	NF/S-L, 150V, 15A, 100W, B=5000	16j	Nec	BDV67D, 2SD1027, 2SD1297, 2SD1515
2SD13	Si-N	NF/S-L, 35V, 10A, 100W	38a	Mat	(BD245, BDV91, 2SC2681)
2SD130	Si-N	=2SD129: 60V	22a	Tos	BD241A, BD535, BD935, 2N4232..33, ++
2SD1300	Si-N+Di+Rbe=27	TV-HA, 1500V, 3A, 50W	23a	Hit	BU206(A), 2SC3023..24, 2SD849..850, ++
2SD1301	Si-N+Di+Rbe=27	TV-HA, 1500V, 2A, 45W	23a	Mat	BU208D, 2SD993
2SD1302	Si-N	lo-sat, 25V, 0,5A, 0,6W, 200MHz	7c	Mat	—
2SD1303	Si-N	NF-Tr/E, 20V, 1A, 1W	7c(9mm)	Mat	2SC2236, 2SD663, 2SD1247, 2SD1331, ++
2SD1304	Si-N	SMD, int.Z-Di, 20V, 0,1A, 150MHz	35a	Mat	(BC846..846, BCW31..33, 2SC1622,++)
2SD1305	Si-N	SMD, 185/185V, 0,15A, 120MHz	35a	Mat	BFN24, BFN26, 2SC3360
2SD1306	Si-N	SMD, Uni, 30V, 0,7A, 250MHz	35a	Hit	BCW65..68
2SD1307	Si-N-Darl	S-L, 350/300V, 6A, 35W, B=2500	17j	Mat	BU910..912, 2SD835, 2SD1089, 2SD1114, ++
2SD1306	Si-N-Darl+Di	NF/S-L, 100V, ±5A, 30W, B=2k..20k	22c(A)	Nec	BDX53F, 2SD1025, 2SD1590..1591
2SD1309	Si-N-Darl+Di	NF/S-L, 150V, ±8A, 40W, B=2k..15k	22c(A)	Nec	BDX53F, 2SD1025, 2SD1500
2SD131	Si-N	NF/S-L, 100V, 5A, 50W, 20MHz	23a	Tos	BD245C, BDV95, BDX95, 2N5758..80, ++
2SD1310	Si-N	NF/S-L, 80V, 3A, 30W, 16MHz	15j	Nec	BD241A, BD535, BD539A, BD935, ++
2SD1311	Si-N	NF/S-L, 100V, 4A, 40W, 20MHz	15j	Nec	BD241C, BD539C, BD937, 2SD712, ++
2SD1312	Si-N	NF-Tr/E, 120V, 1A, 1W, 120MHz	9b	Nec	2N3700..01, 2SC2383, 2SC3228, 2SD667
2SD1313	Si-N	S-L, 800/350V, 25A, 200W, 0,8/3,5µs	77j	Tos	2SC3989

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2SD1314	Si-N-Darl	S-L, +Di(E→B), 600/450V, 15A, 150W	77c(A)	Tos	—
2SD1315	Si-N-Darl	NF/S-L, 150V, 5A, 40W, 20MHz, B>5000	22c(A)	Mat	2SD1590, (2SD1169)
2SD1316	Si-N-Darl+Di	int.Z-Diode, 30V, 2A, 35W, B>1000	30c	Mat	(BD713, BDW23, BDW53, BDW63,++)
2SD1317	Si-N-Darl+Di	int.Z-Diode, 30V, 4A, 40W, B>1000	30c	Mat	(BD713, BDW23, BDW53, BDW63,++)
2SD1318	Si-N-Darl+Di	int Z-Diode, 30V, 8A, 45W, B>1000	30c	Mat	(BD643, BD895, BDW73, BDX53,++)
2SD1319	Si-N-Darl+Di	int Z-Diode, 60V, 2A, 35W, B>1000	30c(I)	Mat	(BD715, BDW23A, BDW53A, BDW63A,++)
2SD132	Si-N	NF/S-L, 100V, 20A, 150W	68a	Nec	2SD363, 2SD372
2SD1320	Si-N-Darl+Di	int.Z-Diode, 60V, 4A, 40W, B>1000	30c(I)	Mat	(BD715, BDW23A, BDW53A, BDW63A,++)
2SD1321	Si-N-Darl+Di	int.Z-Diode, 60V, 8A, 45W, B>1000	30c(I)	Mat	(BD645, BD697, BDW73A, BDX53A,++)
2SD1322	Si-N-Darl+Di	=2SD1316:	15c(I)	Mat	—
2SD1323	Si-N-Darl+Di	=2SD1317:	15c(I)	Mat	—
2SD1324	Si-N-Darl+Di	=2SD1318:	15c(I)	Mat	—
2SD1325	Si-N-Darl+Di	=2SD1319:	15c(I)	Mat	—
2SD1326	Si-N-Darl+Di	=2SD1320:	15c(I)	Mat	—
2SD1327	Si-N-Darl+Di	=2SD1321:	15c(I)	Mat	—
2SD1328	Si-N	SMD, Uni, 25V, 0,5A, 200MHz, Ron=1Ω	35a	Mat	(BC817..818, BCX19..20, 2SC3325,++)
2SD1329	Si-N-Darl+Di	int.C6419Z-Diode, 50V, 6A, 40W, B>2000	30c(I)	Hit	(BD645, BD897, BDW23A, BDW63A, ++)
2SD1330	Si-N	=2SD1302:	9c	Mat	→2SD1302
2SD1331	Si-N	NF-Tr/E, 40V, 1,5A, 0,9W	7c(9mm)	Hit	2SC4488, 2SD1051, 2SD1148, 2SD1207, ++
2SD1332	Si-N	NF/S-L, 100V, 5A, 60W, 20MHz	18j	Mat	BD245C, 2SD718, 2SD895..896, 2SD731, ++
2SD1333	Si-N	NF/S-L, 120V, 6A, 70W	18j	Mat	BD245C, 2SD718, 2SD896, 2SD731, ++
2SD1334	Si-N	NF/S-L, 140V, 7A, 80W	18j	Mat	BD245D, 2SD1046..1047, 2SD731, ++
2SD1335	Si-N	NF/S-L, 150V, 9A, 100W	18j	Mat	BD245D, 2SC2987(A), 2SC2838, 2SD1047
2SD1336	Si-N-Darl+Di	NF/S-L, 150/100V, 6A, 35W, B>1500	22c(A)	Mat	2SD1590, (2SD1023, 2SD1025, 2SD1113,++)
2SD1336A	Si-N-Darl+Di	300/250V, 6A	15c(K)		2SD1792, (2SD991, 2SD1088, 2SD1113,++)
2SD1337	Si-N	TV-HA, 1500/600V, 2,5A, 50W	23a	Say	BU205..206, 2SC3023..3024, 2SD627, ++
2SD1338	Si-N+Di	TV-HA, 1500/600V, 2,5A, 50W	23a	Say	BU206D, BU800, 2SD993, 2SD1301
2SD1339	Si-N	TV-HA, 1500/600V, 3,5A, 50W	23a	Say	BU208..209(A), 2SD849..850, 2SD783, ++
2SD134	Ge-N	S, 60V, 5mA, 0,03W	≈2a	Son	—
2SD1340	Si-N+Di	TV-HA, 1500/600V, 3,5A, 50W	23a	Say	BU208D, BU800, 2SD993, 2SD1171..75, ++
2SD1341	Si-N	TV-HA, 1500/600V, 5A, 50W	23a	Say	BU208(A), BU508(A), 2SC2928, 2SD954, ++
2SD1342	Si-N+Di+Rbe=27	TV-HA, 1500/600V, 5A, 50W	23a	Say	BU208D, BU508D, BU800, 2SD1171..75
2SD1343	Si-N	TV-HA, 1500/600V, 6A, 50W	23a	Say	BU508(A), 2SC3025..3026, 2SD821..822
2SD1344	Si-N+Di+Rbe=27	TV-HA, 1500/600V, 6A, 50W	23a	Say	BU508D, 2SD903..904
2SD1345	Si-N	NF/S-L, 60V, 7A, 40W, 10MHz, 0,2/1,2µs	17j	Shi	BD243A, BD543A, BD797, 2SC3254, ++
2SD1346	Si-N	TV-HA, 1400V, 2,5A, 40W	17j	Mat	BU505
2SD1347	Si-N	NF/S, Io-sat, 60V, 3A, 1W, 150MHz	7c(9mm)	Say	2SC4487, 2SC4482, 2SD1145
2SD1348	Si-N	=2SD1347: 4A, 10W	14h	Say	(BD785, BD787, BD789, MJE240..244,+)
2SD1349	Si-N-Darl	S-L, 500V, 7A, 50W, 11MHz, B>150	22c(E)	Shi	BU810, 2SD1533
2SD1350	Si-N	S, 400/400V, 0,5A, 1W, 55MHz	9c	Mat	2SC4645
2SD1350A	Si-N	=2SD1350: 600/500V	9c		—
2SD1351	Si-N	NF/S-L, 60V, 3A, 30W, 3MHz	17j		BD241A, BD539A, BD535, BD935, ++
2SD1352	Si-N	NF/S-L, 80V, 4A, 30W, 8MHz	17j		BD243B, BD539B, BD537, BD951, ++
2SD1353	Si-N	S-L, hi-beta, 50V, 3A, 30W, 5MHz, B=600	≈15j	Tos	2SD1052, 2SC1983, 2SD1943, 2SD1157
2SD1354	Si-N	NF/S-L, 60V, 3A, 30W, 3MHz	≈15j	Tos	BD241A, BD539A, BD535, BD935, ++
2SD1355	Si-N	NF/S-L, 100V, 5A, 40W, 12MHz	≈15j	Tos	BD243C, BD539C, BD543C, BD953, ++
2SD1356	Si-N	NF/S-L, 80V, 4A, 30W, 8MHz	≈15j	Tos	BD243B, BD539B, BD543B, BD951, ++
2SD1357	Si-N-Darl+Di	NF/S-L, 100V, 7A, 40W, B=6000	≈15j	Tos	BD649, BD901, BDW73C, BDX53C, ++
2SD1358	Si-N-Darl+Di	NF/S-L, 80V, 7A, 40W, B=6000	≈15j	Tos	BD647, BD899, BDW73B, BDX53B, ++
2SD1359	Si-N-Darl+Di	NF/S-L, 60V, 7A, 40W, B=6000	≈15j	Tos	BD645, BD897, BDW73A, BDX53A, ++
2SD136	Si-N	Vid-L, 200V, 0,1A, 4W, 20MHz	≈22	Fui	(BF415, BF417, BF458..459,++)
2SD1360	Si-N-Darl+Di	S-L, 600/400V, 6A, 30W, B=1000	≈15j	Tos	BU810, 2SC3579, 2SD798..799
2SD1361	Si-N-Darl	S-L, 300/250V, 6A, 30W, B=5000	≈15j	Tos	BU910..912, 2SD1088..69, 2SD1113..14, ++
2SD1362	Si-N	Io-sat, 100V, 7A, 40W, 10MHz	≈15j	Tos	2SD1237L
2SD1363	Si-N	Io-sat, 70V, 7A, 40W, 10MHz	≈15j	Tos	2SC3254, 2SD1237L
2SD1364	Si-N	AMP, 300/150V, 7A, 40W	15c	Tos	BU408..408, 2SC3590..91, 2SD1163, ++
2SD1365	Si-N	S-L, 800/400V, 3A, 40W, <1/8µs	≈15j	Tos	BUT11(A), BUV46(A), 2SC3086, 2SC3490++
2SD1366	Si-N	SMD, NF, 25V, 1A, 240MHz	39b	Hit	BC868, BCX54..56, BCX68, 2SC3444, ++
2SD1366A	Si-N	=2SD1366: 30V	39b		BCX54..56, 2SC2873, 2SC3444, 2SD874A, ++
2SD1367	Si-N	SMD, NF, 20V, 2A, 100MHz	39b	Hit	2SC2883, 2SC3443, 2SC3439, 2SC2982
2SD1368	Si-N	SMD, NF, 100V, 1A, 100MHz	39b	Hit	BCX56, 2SD1005, 2SD1368, 2SD1418..1419
2SD1369	Si-N-Darl+Di	NF/S-L, 60V, 3A, 25W, B=5000	≈15j	Tos	BD715, BDW23A, BDW53A, BDW63A, ++
2SD137	Si-N	=2SD136: 300V	≈22	Fui	(BF417, BF459, 2SC3417, 2SC3503,++)
2SD1370	Si-N-Darl+Di	NF/S-L, 100V, 4A, 30W, B=4000	≈15j	Tos	BDW23C, BDW53C, BDW63C, 2SD837B, ++
2SD1371	Si-N	NF/S-L, 300/300V, 2A, 40W, 5MHz	17j	Say	TIP75(A..C), BUT93, 2SC2023, 2SC3055++
2SD1372	Si-N	NF/S-L, 300/300V, 4A, 50W, 5MHz	17j	Say	TIP75(A..C), BUT93, 2SC2907, 2SC2440++

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2SD1373	Si-N	NF/S-L, 300/300V, 4A, 50W, 5MHz	18j	Say	BUW11(A), TIP51..54, 2SC2624, ++
2SD1374	Si-N	NF/S-L, 300/300V, 3A, 50W	23a	Say	BUW11(A), TIP51..54, 2SD632, ++
2SD1375	Si-N	NF/S-L, 300/300V, 4A, 90W	23a	Say	BUW11(A), TIP51..54, 2SD632, ++
2SD1376	Si-N-Darl+Di	NF/S-L, 120/120V, 1,5A, 20W, B>2000	14b(A)	Hit	2SD985..986, 2SD1953, 2SD2019
2SD1377	Si-N-Darl	NF/S-L, 120/120V, 8A, 40W, B>1000	17c(A)	Hit	BD651, BDT21, BDW73D, BDX53D, ++
2SD1378	Si-N	NF-L, 80V, 0,7A, 10W, 120MHz	14h	Rhm	BD139, BD230, 2SD1382, 2SD1684, ++
2SD1379	Si-N-Darl	NF/S-L, 40V, 2A, 10W, 150MHz, B>4000	14b(A)	Rhm	BD775, 2SC4341, 2SD1438, 2SD1953, ++
2SD138	Si-N	NF/Vid-L, 200/200V, 1A, 30W	22a	Fui	BUW40(A,B), TIP47..50, 2SC2020, ++
2SD1380	Si-N	NF/S-L, 40V, 2A, 10W, 100MHz	14h	Rhm	BD375, 2SD1177..78, 2SD1506, 2SD1818,
2SD1381	Si-N	NF/S-L, 120V, 1A, 5W, 100MHz	14b	Rhm	2SC3421, 2SD1684
2SD1382	Si-N	=2SD1381: 10W	14h	Rhm	2SC2690(A), 2SC2803, 2SD781
2SD1383	Si-N-Darl	SMD, Uni, 40V, 0,3A, 250MHz, B>1000	35a(L)	Rhm	—
2SD1383K	Si-N-Darl	=2SD1383:	35a(L)		BCV27, BCV47, 2SD1478A
2SD1384	Si-N	NF-Tr/E, 40V, 2A, 0,75W, 100MHz	7c(9mm)	Rhm	2SC3328, 2SC4145, 2SD1146, 2SD1207, ++
2SD1385	Si-N	NF, Vid, 400/400V, 0,1A, 1W, 40MHz	9c	Mat	MPS-A45, 2SC2267, 2SC3118, 2SC3469
2SD1386	Si-N-Darl+Di	NF/S-L, 140V, 8A, 50W, B=4000	17j	Hit	BDX53E,F, 2SD1590..91, 2SD1756
2SD1387	Si-N	NF-Tr/E, 20V, 2A, 0,7W, B=250	7c	Say	2SC3225, 2SC3573, 2SD1207, 2SD1835, ++
2SD1388	Si-N	NF-Tr/E, 80V, 1A, 0,7W, B=250	7c	Say	BC337A, BC637, 2SC3939, 2SD1616(A), ++
2SD1389	Si-N	S-L, 1200/650V, 6A, 50W	23a	Sak	BU546, BU903, 2SC3343..44, 2SD1104, ++
2SD139	Si-N	=2SD138: 300/300V	22a	Fui	BUW40(A,B), TIP47..50, 2SC2020, ++
2SD1390	Si-N	TV-HA, 1500/700V, 1A, 40W	17c	Mat	BU505
2SD1391	Si-N	TV-HA, 1500/700V, 5A, 100W	15c	Mat	BU506(A), BU908, 2SC3485..86, 2SD1498..97
2SD1392	Si-N-Darl+Di	int. Z-Di(B→C), 60±10V, 5A, 30W, B>2k	17c(H)	Nec	(BD645, BD897, BDW23A, BDW63A, ++)
2SD1393	Si-N-Darl+Di	int. Z-Di(B→C), 80±10V, 2A, 30W, B>1k	17c(H)	Say	BD715, BDW23A, BDW53A, BDW63A, ++
2SD1394	Si-N-Darl+Di	int. Z-Di(B→C), 80±10V, 3A, 30W, B>1k	17c(H)	Say	BD715, BDW23A, BDW53A, BDW63A, ++
2SD1395	Si-N-Darl+Di	int. Z-Di(B→C), 80±10V, 5A, 40W, B>1k	17c(H)	Say	BD645, BD897, BDW23A, BDW63A, ++
2SD1396	Si-N+Di+Rbe≈50	TV-HA, 1500/800V, 2,5A, 80W	16c	Say	BU705D, 2SC3479, 2SD1290..91, 2SD1876
2SD1397	Si-N+Di+Rbe≈50	TV-HA, 1500/800V, 3,5A, 80W	16c	Say	BU706D, 2SC3480, 2SD1729, 2SD1877
2SD1398	Si-N+Di+Rbe≈50	TV-HA, 1500/800V, 5A, 80W	16c	Say	BU508D, 2SC3481, 2SD1730, 2SD1878
2SD1399	Si-N+Di+Rbe≈50	TV-HA, 1500/800V, 6A, 80W	16c	Say	BU508D, 2SC3482, 2SD1732, 2SD1879
2SD14	Si-N	NF/S-L, 75V, 10A, 100W	38a	Mat	(BD245B, BDV93, 2SC2681)
2SD1400	Si-N	TV-HA, 1500/800, 2,5A, 80W	77c	Say	BU705, 2SC3483, 2SD1493..94
2SD1401	Si-N	TV-HA, 1500/800V, 3,5A, 50W	77c	Say	BU508A, BU908, 2SC3484..86, 2SD1495
2SD1402	Si-N	TV-HA, 1500/800V, 5A, 120W	77c	Say	BU508A, BU908, 2SC3485..86, 2SD1498..97
2SD1403	Si-N	TV-HA, 1500/800V, 6A, 120W	77c	Say	BU508A, BU908, 2SC3486, 2SD1497
2SD1404	Si-N	TV-HA, 300/150V, 7/15A, 25W, 18MHz	17c	Tos	(BU406..406, 2SC3590..91, 2SD864..85, +)
2SD1405	Si-N	=2SD1353: Iso, 25W	17c	Tos	2SC3577, 2SC3852, 2SD1948, 2SD1972
2SD1406	Si-N	=2SD1354: Iso, 25W	17c	Tos	2SC3299, 2SC3746, 2SD1913, 2SD2012, ++
2SD1407	Si-N	=2SD1355: Iso, 30W	17c	Tos	2SC3891, 2SD1411, 2SD1488, 2SD1940
2SD1408	Si-N	=2SD1356: Iso, 25W	17c	Tos	2SC3891, 2SC3748, 2SC3851, 2SD2000
2SD1409	Si-N-Darl+Di	=2SD1380: Iso, 25W	15c(A)	Tos	(2SC3579, 2SD798..799)
2SD141	Si-N	NF/S-L, 20V, 2A, 15W	22a	Nec	BD239, BD241, BD533, BD933, ++
2SD1410	Si-N-Darl	=2SD1381: Iso, 25W	15c(K)	Tos	2SD2017, (2SD1088, 2SD1113, 2SD1976)
2SD1411	Si-N	NF/S-L, lo-sat, 100V, 7A, 30W, 10MHz	17c	Tos	2SC4550
2SD1412	Si-N	=2SD1411: 70V	17c	Tos	2SC3747
2SD1413	Si-N-Darl+Di	NF/S-L, 80V, 3A, 20W, B>2000	17c	Tos	BDT61F, 2SD1790, 2SD1796, 2SD1987, ++
2SD1414	Si-N-Darl+Di	NF/S-L, 100V, 4A, 20W, B>2000	17c	Tos	2SD1589, 26D1788, 2SD1928, 2SD2015
2SD1415	Si-N-Darl+Di	=2SD1357: Iso, 30W	22c(A)	Tos	2SC4062, 2SD1791, 2SD1830, 2SD2025
2SD1416	Si-N-Darl+Di	=2SD1358: Iso, 30W	22c(A)	Tos	2SC4062, 2SD1791, 2SD1830, 2SD2025
2SD1417	Si-N-Darl+Di	=2SD1359: Iso, 30W	22c(A)	Tos	2SC4062, 2SD1791, 2SD1826, 2SD2025
2SD1418	Si-N	SMD, Uni, 120/80V, 1A, 140MHz	39b	Hit	2SC3646, 2SD1420..1421
2SD1419	Si-N	=2SD1418: 120/100V	39b	Hit	2SC3646, 2SD1420..1421
2SD142	Si-N	=2SD141: 40V	22a	Nec	BD239, BD241, BD533, BD933, ++
2SD1420	Si-N	SMD, NF-Tr/E, 180/120V, 1,5A	39b	Hit	2SC3849
2SD1421	Si-N	=2SD1420: 180/180V	39b	Hit	2SC3649
2SD1422	Si-N	SMD, NF-Tr/E, 100V, 2A	39b	Hit	2SC3647, 2SC4132, 2SD1420..1421
2SD1423	Si-N	=2SD638: 0,3W	40c	Mat	→2SD838
2SD1423A	Si-N	=2SD639: 0,3W	40c		→2SD839
2SD1424	Si-N	=2SD1010:	40c	Mat	→2SD1010
2SD1425	Si-N+Di+Rbe≈50	TV-HA, 1500/800V, 2,5A, 80W	16c	Tos	BU706D, 2SC3479, 2SD1290..91, 2SD1728
2SD1425..1432FI	Si-N	=2SD1425..1432: Iso	18c	Tho	—
2SD1426	Si-N+Di+Rbe≈50	TV-HA, 1500/800V, 3,5A, 80W	18c	Tos	BU706D, 2SC3480, 2SD1729, 2SD1877
2SD1427	Si-N+Di+Rbe≈50	TV-HA, 1500/600V, 5A, 80W	18c	Tos	BU508D, 2SC3481, 2SD1730, 2SD1878
2SD1428	Si-N+Di+Rbe≈50	TV-HA, 1500/800V, 6A, 80W	16c	Tos	BU508D, 2SC3482, 2SD1732, 2SD1879
2SD1429	Si-N	TV-HA, 1500/800V, 2,5A, 80W	77c	Tos	BU705, 2SC3483, 2SD1493..94
2SD143	Si-N	NF/S-L, 80V, 1A, 15W	22a	Nec	BD239B, BD241B, BD537, BD937, ++

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2SD1430	Si-N	TV-HA, 1500/600V, 3,5A, 80W	77c	Tos	BU706, 2SC3484, 2SD1495
2SD1431	Si-N	TV-HA, 1500/600V, 5A, 80W	77c	Tos	BU508A, BU908, 2SC3485..86, 2SC4291,++
2SD1432	Si-N	TV-HA, 1500/600V, 8A, 80W	77c	Tos	BU508A, BU908, 2SC3686, 2SD1496..97,++
2SD1433	Si-N	TV-HA, 1500/600V, 7A, 80W	77c	Tos	BU508A, BU908, S2000A, 2SC3686..87
2SD1434	Si-N	TV-HA, 1700/800V, 5A, 80W	77c	Tos	—
2SD1435	Si-N-Darl+Di	NF/S-L, 100V, 15A, 100W, B>1000	16c(A)	Hit	BDV67A, BDW83C, 2SD1026
2SD1436	Si-N-Darl+Di	NF/S-L, 120V, 10A, 80W, B>1000	16c(A)	Hit	BDV85C, BDV67B, BDW83D, 2SD1210
2SD1437	Si-N	NF/S-L, 80V, 3A, 40W, 8MHz	17j	Rhm	BD241B, BD537, BD539B, BD937,++
2SD1436	Si-N-Darl+Di	NF/S-L, 80V, 2A, 15W, B=5000	14b	Tos	BD679, BD779, 2N6039, 2SD1376
2SD1439	Si-N+Di+Rbe=50	TV-HA, 1500V, 3A, 50W	16c	Mat	BU508D, BU706D, 2SC3480..3482
2SD144	Si-N	=2SD143: 100V	22a	Nec	BD239C, BD241C, BD937, 2SD712,++
2SD1440	Si-N+Di+Rbe=50	TV-HA, 1500V, 3A, 50W	16c	Mat	BU508D, BU706D, 2SC3480..3482
2SD1441	Si-N+Di+Rbe=50	TV-HA, 1500V, 4A, 70W	16c	Mat, Tho	BU508D, BU706D, 2SC3480..3482
2SD1442	Si-N	NF/S-L, Io-sat, 40V, 7A, 30W, 150MHz	17j	Mat	2SC3254, 2SD1235
2SD1442A	Si-N	=2SD1442: 50V	17j		2SC3254, 2SD1235
2SD1443	Si-N	NF/S-L, Io-sat, 40V, 10A, 40W, 120MHz	17j	Mat	2SC3255, 2SC3345, 2SD1212
2SD1443A	Si-N	=2SD1443: 50V	17j		2SC3255, 2SC3345, 2SD1212
2SD1444(A)	Si-N	=2SD1442: Iso	17c	Mat	2SC3747, 2SC4327
2SD1445(A)	Si-N	=2SD1443(A): Iso	17c	Mat	2SC3709, 2SC4064..65
2SD1446	Si-N+Di	AMP, 500/400V, 8A, 40W, B>500	17c	Mat	—
2SD1447	Si-N	NF-Tr/E, 30V, 1A, 0,9W, 100MHz	7c(9mm)	Mit	2SC2236, 2SD863, 2SD1148, 2SD1207,++
2SD1448(Z)	Si-N	NF/S-L, 70V, 3A, 10W, 60MHz	30j	Nec	2SC3303, 2SC3388, 2SD1815..18
2SD1449	Si-N	=2SD958: 0,3W	40c	Mat	→2SD958
2SD1450	Si-N	=2SD1302: 0,3W	40c	Mat	→2SD1302
2SD1451	Si-N	TV-HA, 1500/600V, 1,5A, 50W	77c	Hit	BU705, 2SC3483, 2SD1492..94
2SD1452	Si-N	TV-HA, 1500/600V, 2,5A, 50W	77c	Hit	BU705, 2SC3483, 2SD1493..94
2SD1453	Si-N+Di+Rbe=50	TV-HA, 1500/600V, 3A, 50W	16c	Hit	BU706, 2SC3484, 2SD1495
2SD1454	Si-N	TV-HA, 1500/600V, 4A, 50W	77c	Hit	BU508A, BU706, 2SC3484, 2SD1495
2SD1455	Si-N+Di+Rbe=50	TV-HA, 1500/600V, 5A, 50W	16c	Hit, Tho	BU508A, BU908, 2SC3465..86, 2SD1496..97
2SD1458	Si-N+Di+Rbe=50	TV-HA, 1500/600V, 8A, 50W	16c	Hit	BU508A, BU906, 2SC3486, 2SD1497
2SD1457(A)	Si-N-Darl+Di	NF/S-L, 200V, 8A, 60W, 15MHz, B>700	16c	Mat	(2SD921, 2SD1090, 2SD1122..23)
2SD1458	Si-N	hi-Ueb, hi-beta, 20V, 0,7A, 1W, 55MHz	9c	Mat	2SC3070, 2SC3618, 2SC4204, 2SD1582
2SD1459	Si-N	CTV-VA, NF-E, 150V, 1,5A, 30W, 8MHz	17j	Say	BD239D, 2SC2073, 2SD608(A), 2SD1136,++
2SD146	Si-N	NF/S-L, 40V, 1A, 20W	22a	Fui	BD239, BD241, BD533, BD933,++
2SD1480	Si-N-Darl+Di	S-L, 100V, 30A, 200W, B=4000	23a	Tos	2SD730
2SD1461	Si-N-Darl+Di	S-L, 400V, 5A, 80W, B>400	18j	Mat	BU826, 2SC3261, 2SD663
2SD1462	Si-N	NF/S-L, 20V, 2A, B=400	30j	Nec	2SD1563..84
2SD1463	Si-N	SMD, Uni, 120/100V, 0,05A, 140MHz	39b	Hit	2SC2780, 2SC2880, 2SD1464
2SD1464	Si-N	SMD, Uni, 180/160V, 0,05A, 140MHz	39b	Hit	2SC2880, 2SC4372
2SD1465L,S	Si-N-Darl	NF/S-L, 120V, 1,5A, 20W, B>2000	30j	Hit	2SD1164, (2SD985..986, 2SD1378)
2SD1466	Si-N-Darl+Di	S-L, 500/450V, 15A, 100W, B>200	18j	Hit	BUT51P
2SD1468(S)	Si-N	NF-Tr/E, 30V, 1A, 0,3..0,4W, 150MHz	7c, 41c	Rhm	BC337..338, BC635, BC637, BC639,++
2SD1469(M)	Si-N	=2SD1468: 0,6W	9c	Rhm	BC337..338, BC635, BC637, BC639,++
2SD147	Si-N	=2SD146: 80V	22a	Fui	BD239A, BD241A, BD535, BD935,++
2SD1470	Si-N-Darl	SMD, Uni, 60V, 1A, B=2k..100k	39b	Hit	BST50..52, 2SD1511
2SDA99911471	Si-N-Darl	SMD, Uni, 40V, 0,3A, B=2k..100k	39b	Hit	BCV29, BCV49
2SD1472	Si-N-Darl+Di	SMD, Uni, 120V, 1,5A, B=2k..30k	39b	Hit	—
2SD1473	Si-N	SMD, NF/S, 500/400V, 0,5A	39b	Hit	—
2SD1474	Si-N	hi-Ueb, Io-sat, hi-beta, 100V, 6A, 40W	17c	Mat	(2SC4553, 2SD1947)
2SD1475	Si-N	=2SD1476: Iso	17c	Mat	2SC3691, 2SC3746, 2SC4549, 2SC4596,++
2SD1476	Si-N	NF/S-L, 80V, 4A, 35W, 50MHz	17j	Mat	BD243B, BD537, BD539B, BD951,++
2SD1477	Si-N	Uni, 30V, 0,1A, 0,4W, B=300	9c	Mat	BC186, BC163, BC236, BC548,++
2SD1478	Si-N-Darl	=2SD892: SMD, 200MHz	35a(L)	Mat	BCV27, 2SD1183
2SD1478A	Si-N-Darl	=2SD892A: SMD, 200MHz	35a(L)		BCV47
2SD1479	Si-N	TV-HA, 1500/700V, 2,5A, 80W	77c	Mat	BU705, 2SC3483, 2SD1493..94
2SD146	Si-N	NF/S-L, 70V, 2A, 20W, 1,2MHz, -/5,8µs	22a	Fui	BD239A, BD241A, BD537, BD937,++
2SD1480	Si-N	NF/S-L, 80V, 2A, 25W, 20MHz	17c	Mat	BD936F, 2SD1585, 2SD1985, 2SD2012
2SD1481	Si-N-Darl+Di	int. Z-Di(B→C), 80±10V, 2A, 15W, B>2k	17c(H)	Nec	(BD715, BDW23A, BDW53B, 2SD837,++)
2SD1482	Si-N	SMD, Uni, 40V, 0,1A	35a	Mat	BC846..847, BCW71..72, BCW81,++
2SD1483	Si-N	=2SD1458: SMD	39b	Mat	2SC4390, 2SD1870, 2SD1950
2SD1484	Si-N	SMD, NF, 50V, 0,5A, 250MHz	≈35d	Rhm	—
2SD1484K	Si-N	=2SD1484:	35a		BC817, BCW65..66, 2SC3325, 2SC3441,++
2SD1485	Si-N	=2SD1332:	16c	Mat	2SC4385, 2SD2064, (BD245C, 2SC2837,++)
2SD1486	Si-N	=2SD1333:	16c	Mat	2SC4385, 2SD2064, (BD245D, 2SC3181,++)
2SD1487	Si-N	=2SD1334	16c	Mat	2SC4386, 2SD2052, (BD245D, 2SD1046,++)
2SD1486	Si-N	=2SD1335:	16c	Mat	2SC4386, 2SD2052, (BD245D, 2SC2837,++)

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2SD1489	Si-N	NF-Tr/E, 20V, 2A, 0,75W, 80MHz	7c	Hit	2SC3225, 2SD1100, 2SD1146, 2SD1207, ++
2SD149	Si-N	NF/S, 70V, 1A, 0,8W, 1,2MHz	2a	Fui	BC441, BCX40, 2N1990, 2N2102, ++
2SD1490	Si-N	NF-Tr/E, 70V, 1A, 0,75W, 80MHz	7c	Hit	BC639, 2SD667, 2SD1616(A), 2SD1768, ++
2SD1491	Si-N-Darl+Di	int. Z-Di(B→C), 60±10V, ±2A, 10W, B>2k	14b(H)	Nec	—
2SD1492	Si-N	TV-HA, 1500/600V, 1,5A, 50W	77c	Hit	BU705, 2SC3483
2SD1493	Si-N	TV-HA, 1500/800V, 2,5A, 50W	77c	Hit	BU705, 2SC3483
2SD1494	Si-N	TV-HA, 1500/600V, 3A, 50W	77c	Hit	BU706, 2SC3484
2SD1495	Si-N	TV-HA, 1500/600V, 4A, 50W	77c	Hit	BU508(A), BU706, 2SC3484
2SD1496	Si-N	TV-HA, 1500/600V, 5A, 50W	77c	Hit	BU508(A), BU908, 2SC3485..96, 2SC3685
2SD1497	Si-N	TV-HA, 1500/650A, 50W	77c	Hit	BU508(A), BU908, 2SC3482, 2SC3685
2SD1496	Si-N	TV-HA, 1400/650V, 8A, 50W	77c	Hit	BU508(A), BU908, 2SC3687
2SD1499	Si-N	=2SD1485: 40W	17c	Mat	BD953F, BDT41AF, 2SD1407, 2SD1940, ++
2SD15	Si-N	NF/S-L, 60V, 6A, 80W, <1460/5100ns	23a	Sak	BD245A, BDV91, 2N4914..4915, ++
2SD150	Si-N	NF/S-L, 50V, 1A, 15W, >10MHz	22a	Nec	BD239, 2SC1398, 2SC2591..2592, ++
2SD1500	Si-N-Darl+Di	NF/S-L, 150V, 10A, 40W, B=5000	17j	Tos	2SD1756
2SD1501	Si-N	NF-Tr/E, 70V, 1A, 1W, B=250	9c	Hit	2SD667, 2SD774, 2SD1616(A), 2SD1768, ++
2SD1502	Si-N-Darl	S-L, 300/300V, 0,3A, 15W, B=7000	17j	Nec	2SD1796
2SD1503	Si-N	HV, 900/800V, 6A, 50W	16c	Hit	BU508(A), BU908, 2SC3636, 2SC3642
2SD1504	Si-N	Muting, 30V, 0,5A, 300MHz, Ron=0,5Ω	41c	Hit	(BC337..338, 2SD774, 2SC3377, 2SD1302+)
2SD1505	Si-N	NF/S-L, 60V, 3A, 30W, 90MHz	17j	Rhm	BD241A, BD535, BD935, 2SC3252, ++
2SD1506	Si-N	=2SD1505: 10W	14h	Rhm	BD177, BD439, BD785, 2SD1348, ++
2SD1507(M)	Si-N	=2SD1505: 1W	9c	Rhm	2SC4487, 2SD1145, 2SD1347, 2SD1864
2SD1506	Si-N-Darl	NF/S-L, 30V, 1,5A, 10W, B=7000	14b	Tos	2SD947
2SD1509	Si-N-Darl+Di	NF/S-L, 80V, 2A, 10W, 100MHz, B=5000	30c(A)	Tos	—
2SD151	Si-N	NF/S-L, 100V, 10A, 120W	23a	Nec	BDY53, 2N3055, 2N5632..33, 2SD426, ++
2SD1510	Si-N-Darl+Di	NF/S-L, 60V, 4A, 35W, B>1000	17c(A)	Mat	BDT61F, 2SD1790, 2SD1796, 2SD1987, ++
2SD1511	Si-N-Darl	Uni, 100V, 1A, 150MHz, B>4000	39b	Mat	BST52, 2SD1472
2SD1512	Si-N	=2SD1011:	40c	Mat	→2SD1011
2SD1513	Si-N	Uni, 20V, 2A, 0,75W, 200MHz	7c	Nec	2SC3225, 2SD1100, 2SD1146, 2SD1207, ++
2SD1514	Si-N-Darl	NF/S-L, 100V, 15A, 100W, B=4000	16j	Shi	BDV67A, BDW83C, 2SD1026
2SD1515	Si-N-Darl	=2SD1514: 200V	16j	Shi	2SD1027
2SD1516	Si-N	NF/S-L, Io-sat, 130V, 2A, 25W, 25MHz	17j	Mat	2SD1528
2SD1517	Si-N	=2SD1516: Iso	17c	Mat	2SD1268
2SD1518	Si-N	S-L, 900V, 6A, 50W, 5MHz	18j	Tos	BU426A, BUW11(A), 2SC3153, 2SD1503, ++
2SD1519	Si-N	TV-HA, 1400/600V, 10A, 80W	77j	Tos	BU2520A, 2SC3688
2SD152	Si-N	NF/S-L, 150V, 1A, 15W	22a	Nec	BD239D, 2SC2073, 2SD608(A), 2SD1139, ++
2SD1520L,S	Si-N-Darl+Di	NF/S-L, 100V, 4A, 20W, B>1000	30c(A)	Hit	2SC4345, 2SD1223, (BDW2SC, BDW53C, ++
2SD1521	Si-N-Darl+Di	int. Z-Diode, 50V, 1,5A, 10W, B>2000	14h(H)	Hit	(2SC4341, 2SD1376, 2SD1438)
2SD1522	Si-N-Darl+Di	S-L, 500/450V, 10A, 100W, B=500	77c(A)	Hit	BUT51P, 2SC3262, 2SD979, 2SD1298
2SD1523	Si-N-Darl	S-L, 450/450V, 15A, 100W, B=500	77c(A)	Hit	BUT51P, 2SD1466
2SD1524	Si-N-Darl	S-L, 450/450V, 10A, 100W, B=300	77c(A)	Hit	BUT51P, 2SC3262, 2SD979, 2SD1298
2SD1525	Si-N-Darl+Di	S-L, 100V, 30A, 150W, B=4000	77c	Tos	—
2SD1526	Si-N	NF-Tr/E, 130V, 1A, 1W, 200MHz	9c	Mat	2N3700..01, 2SC2383, 2SC3228, 2SD1812
2SD1527	Si-N	S-L, 1000/1000V, 0,5A, 25W, 5MHz	17j	Hit	(BUV36A, BUX85, 2SC3178, 2SC3531, ++)
2SD1528	Si-N	NF/S-L, Io-sat, 130V, 3A, 30W, 25MHz	17j	Mat	—
2SD1529	Si-N	=2SD1528:	30j	Mat	2SD1254..55
2SD153	Si-N	S-L, 250V, 10A, 120W	49m	Nec	2N5540
2SD1530	Si-N	=2SD1528: Iso	17c	Mat	—
2SD1531	Si-N	NF/S-L, 50V, 2A, 5W, 150MHz	14h	Mat	BD177, BD235, BD377, 2SD1177..78, ++
2SD1532	Si-N-Darl	NF/S-L, 120V, 4A, 30W, B=3000	17j	Sak	BDT21, BDW53D, BDW63D, 2SD1147, ++
2SD1533	Si-N-Darl	S-L, 500/400V, 7A, 50W, 20MHz, B>500	17j	Mat	BU810
2SD1534	Si-N-Darl	=2SD1533:	30j	Mat	2SC4220, 2SC4598, (BU810)
2SD1535	Si-N-Darl	=2SD1533: Iso	22c(E)	Mat	(BU810)
2SD1536(M)	Si-N-Darl	Uni, 40V, 2A, 1W, 150MHz, B>1000	9c	Rhm	2SD1768, 2SD1961, 2SD1931
2SD1537	Si-N	NF/S-L, 40V, 4A, 25W, 120MHz	17j	Mat	2SC2562, 2SC3253, 2SD1235
2SD1537A	Si-N	=2SD1537: 50V	17j	Mat	2SC2562, 2SC3253, 2SD1235
2SD1538(A)	Si-N	=2SD1537(A):	30j	Mat	2SD1903, (2SC2562, 2SC3253, 2SD1235)
2SD1539(A)	Si-N	=2SD1537(A): Iso	17c	Mat	2SC3299, 2SC4327, 2SD1444(A)
2SD154	Si-N	NF/S-L, 60V, 3A, 25W	22a	Nec	BD241B, BD243B, BD537, BD937, ++
2SD1540	Si-N-Darl	NF/S-L, 100V, 6A, 60W, B=800	23a	Tos	BDV65B, BDX83B, TIP142, 2SD1170, ++
2SD1541	Si-N+Di+Rbe≈50	TV-HA, 1500V, 3A, 50W	16c	Mat	BU508DF, 2SC3460, 2SD1554, 2SD1650
2SD1542	Si-N	TV-HA, 1500/600V, 1,5A, 40W	77c	Tos	2SD1653, (BU705, 2SC3483, 2SD1492..94)
2SD1543	Si-N	CTV-HA, 1500/600V, 2,5A, 40W	16c	Tos	BU705F, 2SD1563, (2SC3483, 2SD1493..94)
2SD1544	Si-N	CTV-HA, 1500/600V, 3,5A, 40W	16c	Tos	BU2508AF, BU706F, 2SD1654, (2SC3484)
2SD1545	Si-N	CTV-HA, 1500/600V, 5A, 50W	16c	Tos	BU2508AF, BU706F, 2SC4142, 2SD1655, ++
2SD1548	Si-N	CTV-HA, 1500/800V, 6A, 50W	16c	Tos	BU2508AF, 2SC4143, 2SD1556, 2SD1685, ++

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2SD1547	Si-N	CTV-HA, 1500/600V, 7A, 50W	18c	Tos	BU2508AF, 2SC3895, 2SC4757, 2SD2252, ++
2SD1548	Si-N	CTV-HA, 1400/600V, 10A, 50W	18c	Tos	BU2520AF, BUH715, 2SC3897, 2SC4199(A)+
2SD1549	Si-N	TV-HA, 1000/800V, 5A, 50W	18c	Tos	BU508AF, 2SD1655, (BU908, 2SC3642, ++)
2SD155	Si-N	NF/S-L, 80V, 3A, 25W	22a	Nec	BD241B, BD243B, BD537, BD937, ++
2SD1550	Si-N	TV-HA, 1000/400V, 10A, 50W	18c	Tos	BU2520AF, 2SC4125, (2SC3688, 2SD1519)
2SD1551	Si-N	TV-HA, 1500/600V, 5A, 50W	77c	Tos	BU508AF, 2SC4293..94, 2SD1655, ++
2SD1552	Si-N	TV-HA, 1500/600V, 5A, 50W	77c	Tos	BU508AF, 2SC4293..94, 2SD1655, ++
2SD1553	Si-N+Di+Rbe≈50	TV-HA, 1500/600V, 2,5A, 40W	18c	Tos	BU508DF, BU706DF, 2SD1649, 2SD2089
2SD1554	Si-N+Di+Rbe≈50	TV-HA, 1500/600V, 3,5A, 40W	18c	Tos	BU508DF, BU706DF, 2SD1650, 2SD2089
2SD1555	Si-N+Di+Rbe≈50	TV-HA, 1500/600V, 5A, 50W	18c	Tos	BU508DF, 2SD1651, 2SD2095, 2SD2125
2SD1556	Si-N+Di+Rbe≈50	TV-HA, 1500/600V, 8A, 50W	18c	Tos	BU506DF, 2SC3892A, 2SD1652, 2SD2125
2SD1557	Si-N	NF/S-L, 200V, 2A, 20W, 10MHz	30j	Nec	2SD1033, 2SD1250(A), (2SD1138, ++)
2SD1556	Si-N-Darl	NF/S-L, 80V, 4A, 40W, B>1000	17c(A)	Hit	BD715, BDW23A, BDW53A, 2SD837, ++
2SD1559	Si-N-Darl+Di	NF/S-L, 100V, 20A, 100W, B>1000	18c(A)	Hit	2SD1597
2SD156	Si-N	Vid-L, 200V, 0,1A, 4W(Tc=70°), 20MHz	22a	Fui	2SC1505..1507, 2SC1755..1757, 2SC1819, ++
2SD1562	Si-N	NF-L, 120/120V, 1,5A, 20W, 80MHz	17j	Rhm	BD239D, BD959, 2SC2275, 2SD1138, ++
2SD1562A	Si-N	=2SD1562: 160/180V	17j		BD239D, 2SC2238(A,B), 2SD608(A), 2SD1138++
2SD1563	Si-N	=2SD1562: 10W	14h	Rhm	2SC2690(A), 2SD781
2SD1563A	Si-N	=2SD1563: 160/180V	14h		2SC3117, 2SD669
2SD1564	Si-N-Darl+Di	int. Z-Di(B→C), 50V, 5A, 30W, B=8000	17c	Nec	(BDW23A, BDW83A)
2SD1565	Si-N-Darl+Di	S-L, 100/100V, 5A, 30W, B=8000	17c(A)	Nec	(BDW23C, BDW63C)
2SD1566	Si-N-Darl+Di	NF/S-L, 150V, ±10A, 80W, B=9000	15c	Nec	—
2SD1567	Si-N	NF/S-L, 80V, 3A, 30W, 16MHz	17j	Nec	BD241A, BD535, BD935, 2SC3252, ++
2SD1568	Si-N	NF/S-L, 100V, 4A, 40W, 20MHz	17j	Nec	BD243C, BD537, BD539C, 2SC3253, ++
2SD1569	Si-N	hi-beta, lo-sat, 80V, 3A, 30W, B>800	17j	Nec	—
2SD157	Si-N	=2SD156: 300V	22a	Fui	2SC1505..1507, 2SC1755..1757, 2SC1819, ++
2SD1571	Si-N	S-L, TV-SMPS, 800/400V, 3A, 30W	17c	Tos	BUT11(A)F, 2SC3353, 2SC3749, 2SC4304, ++
2SD1572	Si-N-Darl	NF/S-L, 80V, 8A, 40W, B>1000	17j	Hit	BD845, BD897, BDW73A, BDX53A, ++
2SD1573	Si-N	NF, S, 600/600V, 0,1A, 1W	9c	Hit	—
2SD1574	Si-N-Darl	NF/S-L, 100V, 1A, 10W, B>4000	30j	Mat	2SD1485, 2SD1980
2SD1575	Si-N	TV-HA, 1500/700V, 2A, 40W	17c	Mat	BU505F, (BU508)
2SD1576	Si-N	TV-HA, 1500/700V, 2A, 80W	77c	Mat	2SD1543, 2SD1653, (BU705, 2SC3463, ++)
2SD1577	Si-N	TV-HA, 1500/700V, 5A, 100W	77c	Mat	—
2SD1577FI	Si-N	=2SD1577:	18c	Th	—
2SD1578	Si-N	NF-Tr/E, 30V, 0,7A, 0,5W, B=550	9c	Hit	2SC3225, 2SC4204, 2SC4389, 2SD1984, ++
2SD1579	Si-N-Darl+Di	NF, S, 150V, ±1,5A, 1W, B>2000	9b	Nec	2SD1659, 2SD2213
2SD156	Si-N	NF-E, Vid-L, 200V, 1A, 30W, 15MHz	22a	Fui	BUW40, TIP47..50, 2SC782, 2SC2354, ++
2SD1580	Si-N	NF/S-L, 100V, 7A, 40W, 5MHz	17j	Rhm	BD243C, BD543C, BD801, 2SD550, ++
2SD1581	Si-N	hi-Ueb, hi-beta, 30V, 2A, 1W, 350MHz	9b	Nec	2SC4389, 2SD1561, 2SD1779
2SD1562	Si-N	hi-Ueb, hi-beta, 80V, 1A, 1W, 250MHz	9b	Nec	2SD1779
2SD1583(Z)	Si-N	hi-beta, lo-sat, 30V, 2A, B>800, 270MHz	30j	Nec	2SC3474
2SD1584	Si-N	hi-beta, lo-sat, 80V, 3A, B>800, >50MHz	30j	Nec	2SD1755
2SD1585	Si-N	=2SD1567: Iso, 15W	17c	Nec	2SC3690, 2SC3851..52, 2SD1913
2SD1586	Si-N	=2SD1568: Iso, 20W	17c	Nec	2SC3891, 2SD1407, (BD243C, BD539C, ++)
2SD1587	Si-N	TV, NF-L, 200/150V, 2A, 25W, 5MHz	17c	Nec	2SC4382, (BD239F, 2SC2660, 2SD780, ++)
2SD1588	Si-N	NF/S-L, 100/60V, 7A, 30W	17c	Nec	2SC3568, 2SC3892, 2SC4335, 2SD1411
2SD1589	Si-N-Darl+Di	NF/S-L, 100V, ±5A, 20W, B=8000	22c(A)	Nec	BD647F, 2SD1785, 2SD1829, 2SD1928
2SD159	Si-N	=2SD158: 300V	22a	Fui	BUW40, TIP47..50, 2SC782, 2SC2354, ++
2SD1590	Si-N-Darl+Di	NF/S-L, 150V, 8A, 25W, B=6000	22c(A)	Nec	2SD1591, 2SD1792, 2SD1974
2SD1591	Si-N-Darl+Di	NF/S-L, 150V, 10A, 30W, B=6000	30c(I)	Nec	2SD1794, (2SD1500)
2SD1592	Si-N-Darl	Rbe=500Ω, 500/300V, 5A, 30W, B=1000	17c	Nec	2SD1409
2SD1593	Si-N	hi-beta, lo-sat, 80V, 3A, 110MHz, B>800	17c	Nec	2SD1972, 2SD2127
2SD1594	Si-N	hi-beta, 100V, 8A, 30W, 110MHz, B>800	17c	Nec	2SC4553, 2SD1947
2SD1595	Si-N-Darl+Di	int. Z-Di(B→C), 80V, 5A, 20W, B=6000	17c	Nec	2SD1415..17, 2SD1589, 2SD1826
2SD1597	Si-N-Darl+Di	NF/S-L, 120V, 30A, 80W, B>1000	18c	Hit	—
2SD1598	Si-N-Darl	NF/S-L, 80V, 1A, 10W, B=8000	30j	Nec	2SC2871, 2SD1465, 2SD1164, 2SD1800
2SD1599	Si-N-Darl	NF/S-L, 80V, 4A, 40W, B>1000	17c(A)	Hit	BDW23B, BDW53B, BDW63B, 2SD637A, ++
2SD16	Si-N	=2SD15: 100V	23a	Sak	BD245C, BDV95, 2N5758..5759, ++
2SD160	Si-N	NF/S-L, 100V, 1,5A, 25W, -/3,5µs	2a	Fui	(BD237, BD239C, BD241C, BD937, ++)
2SD1600	Si-N-Darl	NF/S-L, 80V, 8A, 40W, B>1000	17c(A)	Hit	BD647, BD899, BDW73B, BDX53B, ++
2SD1601	Si-N-Darl+Di	NF/S-L, 60V, 4A, 40W, B>1000	17c(A)	Hit	BD715, BDW23A, BDW53A, 2SD837, ++
2SD1602	Si-N-Darl+Di	=2SD1801: 80V	17c(A)	Hit	BD717, BDW23B, BDW53B, 2SD837A, ++
2SD1603	Si-N-Darl+Di	NF/S-L, 80V, 8A, 40W, B>1000	17c(A)	Hit	BD645, BD897, BDW73A, BDX53A, ++
2SD1604	Si-N-Darl+Di	=2SD1604: 80V	17c(A)	Hit	BD647, BD899, BDW73B, BDX53B, ++
2SD1605	Si-N-Darl+Di	NF/S-L, 120V, 3A, 30W, B>1000	17c(A)	Hit	BDW53D, BDW63D, 2SD830, 2SD1147, ++
2SD1606	Si-N-Darl+Di	NF/S-L, 120V, 8A, 40W, B>1000	17c(A)	Hit	BDT21, BDW63D, 2SD630, 2SD1147, ++

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2SD1607	Si-N-Darl+Di	NF/S-L 120V, 10A, 40W, B=5000	17c(A)	Hit	BDT63C, BDT65D, BDX33D, 2SD1126
2SD1608	Si-N-Darl	NF/S-L, 120V, 8A, 50W, 20MHz, B>5000	17c(A)	Mat	BD649F, BDT63CF, 2SD1773, 2SD1590,++
2SD1609	Si-N	NF/S-L, 160/160V, 0,1A, 140MHz	14h	Hit	BF415, BF457..459, 2SC3416, 2SC3502,++
2SD161	Si-N	NF/S-L, 120V, 10A, 100W, -/5µs	23a	Fui	BDX11, 2N3442, 2SD551, 2SD732..733,++
2SD1610	Si-N	=2SD1609: 200/200V	14h	Hit	BF415, BF458..459, 2SC3416, 2SC3502,++
2SD1611	Si-N-Darl+Di	S-L, 500/400V, 6A, 40W, 15MHz, B>500	30j	Mat	—
2SD1612	Si-N-Darl+Di	NF/S-L, 120V, 6A, 40W, B=5000	15j	Hit	BDW63D, BDW73D, BDX53D, 2SD1147,++
2SD1613	Si-N-Darl+Di	NF/S-L, 120V, 8A, 40W, B=5000	15j	Hit	BDW73D, BDX33D, BDX53D, 2SD651,++
2SD1614	Si-N	SMD, Uni, 40V, 2A, 200MHz	39b	Nec	2SC2873, 2SD1119, 2SD1766
2SD1615	Si-N	SMD, Uni, lo-sat, 60V, 1A, >80MHz	39b	Nec	2SC3444, 2SD1622..23, 2SC4409
2SD1615A	Si-N	=2SD1615: 120V	39b		(2SC3646, 2SD1418..19)
2SD1616	Si-N	lo-sat, 60V, 1A, 0,75W, 160MHz	7c	Nec	2SC4485..66, 2SD1207, 2SD1835
2SD1616A	Si-N	=2SD1616: 120V	7c		2SC4488..89, (2SD1812, 2SD1857,++)
2SD1617	Si-N	NF-E, lo-sat, 40V, 3A, 1W, 200MHz	9b	Nec	2SC4467, 2SD1347
2SD1618	Si-N	SMD, NF, lo-sat, 20V, 0,7A, 250MHz	39b	Say	2SC2982, 2SC4390
2SD1619	Si-N	SMD, NF, 25V, 1A, 180MHz	39b	Say	BC868, BCX68, BCX54..56, 2SC3444,++
2SD162	Ge-N	NF, 20V, 0,03A, 0,85W	37a	Fui	—
2SD1620	Si-N	SMD, NF, lo-sat, 30V, 3A, 200MHz	39b	Say	2SD1624
2SD1621	Si-N	SMD, NF, lo-sat, 30V, 2A, 150MHz	39b	Say	2SC2982, 2SD1620
2SD1622	Si-N	SMD, NF, lo-sat, 60V, 1A, 150MHz	39b	Say	—
2SD1623	Si-N	SMD, NF, lo-sat, 60V, 2A, 150MHz	39b	Say	2SC4409
2SD1624	Si-N	SMD, NF, lo-sat, 60V, 3A, 150MHz	39b	Say	—
2SD1625	Si-N-Darl	SMD, NF, 60V, 0,7A, B>5000, 200MHz	39b(C)	Say	BST51..52
2SD1626	Si-N-Darl	SMD, NF, 80V, 1,5A, B>4000, 120MHz	39b(C)	Say	2SD1472
2SD1627	Si-N-Darl	SMD, NF, 30V, 2A, B>4000, 120MHz	39b(C)	Say	2SD1764
2SD1628	Si-N	SMD, NF, lo-sat, 60V, 5A, 30/340ns	39b	Say	—
2SD1629	Si-N-Darl+Di	Z-Di(B→C), 60V, ±1,2A, 10W, B>2000	14b(H)	Nec	—
2SD163	Si-N	NF/S-L, 60V, 10A, 100W, 1,56/6µs	23a	Sak	BD311, 2N3055, 2N5632..33, 2SD426,++
2SD1630	Si-N-Darl+Di	Z-Di(B→C), 60V, ±1A, 10W, B>2000	14b(H)	Nec	—
2SD1631	Si-N-Darl	=2SD1140: 1W	9c	Tos	2SD1536, 2SD1786, 2SD1861, 2SD2046,++
2SD1632	Si-N+Di	S-L, TV-HA, 1500V, 4A, 70W	16c	Mat	BU508DF, 2SD1554..55, 2SD1850, 2SD2089
2SD1633	Si-N-Darl	NF/S-L, 100V, 5A, 30W, 15MHz, B>1500	22c(A)	Mat	2SD1589, 2SD1765, 2SD1629, 2SD1928
2SD1634	Si-N-Darl	NF/S-L, 100V, 8A, 50W, 15MHz, B>1500	22c(A)	Mat	2SC4063, 2SD1415, 2SD1590..91, 2SD1791
2SD1635	Si-N-Darl+Di	S-L, 1500V, 5A, 100W, B=100	23a	Mat	—
2SD1636	Si-N	NF/Vid, 300V, 0,07A, 1W, 80MHz	9c	Mat	BF299, BF487, BF420A, 2SC3468,++
2SD1637	Si-N-Darl+Di	int. Z-Diode, 60V, 2A, 15W, B>1000	14b(H)	Rhm	—
2SD1638	Si-N-Darl+Di	NF/S-L, 100V, 2A, 15W, B=1k..10k	14b	Rhm	2SD1376, 2SD1953
2SD1639	Si-N	NF/S-L, 100V, 2,2A, 10W(Tc=25°)	2a	Mit	BUY41, 2N4300, 2SC1680
2SD164	Si-N	=2SD163: 100V	23a	Sak	BD317, 2N3055, 2N5632..33, 2SD426,++
2SD1640	Si-N-Darl+Di	NF/S-L, 120V, 2A, 150MHz, B>4000	14b	Mat	—
2SD1641	Si-N	hi-beta, Z-Di, 55V, 4A, 60W, 45MHz, B>500	18j	Mat	—
2SD1642	Si-N	NF, 100V, 2A, 0,7W	7c	Hit	2SD1015, (BD529, 2SD1281..1282,++)
2SD1643	Si-N	hi-beta, 60V, 3A, 50W, 50MHz, B>500	16c	Mat	—
2SD1643A	Si-N	=2SD1643: 100V	16c		—
2SD1644	Si-N-Darl	SMD, +Z-Di(B→C), 95V, 1A, B=10000	39b	Mat	BST52
2SD1645	Si-N-Darl	int Z-Di, 60V, 1A, 150MHz, B=4k..40k	14b(H)	Mat	—
2SD1646	Si-N-Darl+Di	=2SD1638: 25W	17c(A)	Rhm	—
2SD1647	Si-N-Darl+Di	=2SD1637: 25W	17c(H)	Rhm	—
2SD1648	Si-N	SMD, NF, 30V, 0,02A	35c	Say	—
2SD1649	Si-N+Di+Rbe≈50	TV-HA, 1500/800V, 2,5A, 50W	16c	Say	2SD708DF, 2SD1553, 2SD2089
2SD165	Si-N	=2SD163: 150V	23a	Sak	BDX11, 2N3442, 2SD551, 2SD732..733,++
2SD1650	Si-N+Di+Rbe≈50	TV-HA, 1500/800V, 3,5A, 50W	19c	Say	BU706DF, 2SD1554, 2SD2089
2SD1650Ft	Si-N+Di	=2SD1650	16c	The	BU706DF, 2SD1554, 2SD2089
2SD1651	Si-N+Di+Rbe≈50	TV-HA, 1500/800V, 5A, 60W	16c	Say	BU508DF, 2SD1555, 2SD2095, 2SD2125
2SD1652	Si-N+Di+Rbe≈50	TV-HA, 1500/800V, 6A, 60W	16c	Say	BU508DF, 2SC4293, 2SD1556, 2SD2125
2SD1653	Si-N	TV-HA, 1500/800V, 2,5A, 60W	19c	Say	BU705F, 2SD1543, (2SC3483, 2SD1493..94)
2SD1654	Si-N	TV-HA, 1500/800V, 3,5A, 50W	16c	Say	BU708F, 2SD1544, (2SC3484, 2SD1495,++)
2SD1655	Si-N	TV-HA, 1500/800V, 5A, 50W	16c	Say	BU508AF, 2SC4142..43, 2SD1545..46,++
2SD1656	Si-N	TV-HA, 1500/800V, 6A, 50W	16c	Say	BU508AF, 2SC4294, 2SD1546..47,++
2SD1657	Si-N	NF, 25V, 0,7A, 0,6W, 150MHz	7c	Mat	BC337..338, BC635, BC637, BC639,++
2SD1658	Si-N-Darl+Di	+Z-Di(B→C), 60V, 2A, 10W, B=5000	14b(H)	Tos	—
2SD1659	Si-N-Darl+Di	NF/S, 150V, ±1,5A, 1W, B=10000	9b	Nec	2SD1579, 2SC2213
2SD166	Si-N	=2SD163: 200V	23a	Sak	MJ15015, BDW18, 2SC1585..66, 2SD665,++
2SD1660(M)	Si-N-Darl+Di	=2SD1636: 1W	9c	Rhm	2SD1978, 2SD1981, 2SD2067
2SD1661(M)	Si-N-Darl+Di	=2SD1637: 1W	9c	Rhm	—
2SD1662	Si-N-Darl+Di	NF/S-L, 100V, 15A, 100W, B=5000	16c(A)	Tos	BDV67A, BDW83C, 2SD1026

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2SD1663	Si-N	TV-HA, 1500V, 5A, 80W	16c	Mat	BU508AF, BU706, 2SC3894, 2SD1655..56++
2SD1664	Si-N	SMD, NF, 40V, 1A, 150MHz	39b	Rhm	BCX54..56, 2SC3444, 2SD874A,++
2SD1665	Si-N	Uni, 120/120V, 1,5A, 1W, 80MHz	9c	Rhm	2SD1015, 2SD1812, 2SD1857
2SD1665A(M)	Si-N	=2SD1665: 160/160V	9c	Say	2SD1612, 2SD1657A
2SD1666	Si-N	NF/S-L, 60V, 3A, 25W, 8MHz	17c	Say	2SC3299, 2SC3852, 2SD1565, 2SD2012, ++
2SD1667	Si-N	S-L, lo-sat, 60V, 5A, 25W, 30MHz	17c	Say	2SC3299, 2SC3746, 2SD1411
2SD1668	Si-N	S-L, lo-sat, 60V, 7A, 30W, 10MHz	17c	Say	2SC3747, 2SD1412
2SD1669	Si-N	S-L, lo-sat, 60V, 12A, 30W, 10MHz	17c	Say	2SC4065
2SD167	Ge-N	NF-Tr/E, 20V, 0,5A, 0,2W	2a	Fui	AC127, AC176, AC167, 2SD72, 2SD352
2SD1670	Si-N-Darl+Di	S-L, 150/100V, ±10A, 65W, B=9000	16c	Nec	2SD1895
2SD1671	Si-N-Darl+Di	S-L, 150/100V, ±15A, 70W, B=3500	16c	Nec	—
2SD1672	Si-N-Darl+Di	S-L, 150/100V, 25A, 70W, B=3500	16c	Nec	—
2SD1673	Si-N-Darl+Di	S-L, 500/400V, 10A, 70W, B=600	16c	Nec	(BU922, BUW81, MJ10003, 2SD885,++)
2SD1676	Si-N+R	S, 20V, 0,6A, 0,3W, Rb=Rbe=6,8kΩ	41c	Hit	(→BC338)
2SD1677	Si-N	TV-HA, 1500/600V, 5A, 100W	16c	Say	BU508A, BU906, 2SC3481..3482,++
2SD1678	Si-N-Darl+Di	NF/S-L, 100V, 15A, 100W, B=5000	20j	Tos	2SD1067
2SD1679	Si-N	SMD, int Z-Di(C→B), 18V, 0,5A, 170MHz	35a	Mat	—
2SD168	Si-N-Darl	NF/S-L, 60V, 10A, 50W, B=2500	23a	Fui	BDV85A, BDX83B, BDX65B, MJ3000..01,++
2SD1660	Si-N	HV, S-L, 1000/450V, 8A, 100W, 30MHz	16c	Mat	(BU124(A), 2SC2305, 2SC2656, 2SD917)
2SD1661	Si-N	NF/S-L, lo-sat, 20V, 1,2A, 10W, 150MHz	14b	Say	(BD135, BD185, BD226, BD235,++)
2SD1682	Si-N	S-L, lo-sat, 60V, 2,5A, 10W, 140MHz	14b		(BD177, BD439, BD765, 2SD1348,++)
2SD1683	Si-N	S-L, lo-sat, 60V, 4A, 10W, 150MHz	14b	Say	(BD189, BD439, BD785, 2SD1348,++)
2SD1664	Si-N	NF/S-L, lo-sat, 120V, 1,5A, 10W, 120MHz	14b	Say	(BD233, 2SC2481, 2SC2690(A), 2SC3621)
2SD1685	Si-N	NF/S-L, lo-sat, 60V, 5A, 10W, 120MHz	14b	Say	(BDX35..37, 2SD82S)
2SD1666	Si-N-Darl+Di	NF/S-L, 120V, 3A, 20W, B=5000	15c	Hit	2SD1785, 2SD2015, (BDW53D, BDW83D,++)
2SD1687	Si-N-Darl+Di	NF/S-L, 60V, 3A, 20W, B=5000	15c	Hit	2SD1413, 2SD1790, 2SD1796, 2SD1987, ++
2SD1668	Si-N-Darl+Di	NF/S-L, 120V, 8A, 25W, B=7000	15c	Hit	2SD1590..91, (BD651, BDW73D++)
2SD1689	Si-N-Darl+Di	NF/S-L, 120V, 8A, 25W, B=5000	15c	Hit	2SD1785, 2SD1338, (BD851, BDW63D,++)
2SD1690	Si-N-Darl+Di	NF/S-L, 120V, 8A, 25W, B=5000	15c	Hit	2SD1590..91, 2SD1792, (BD651, BDW73D++)
2SD1691	Si-N	lo-sat, 60V, 5A, 20W, <1/3,5µs	14h	Nec	2SD826
2SD1692	Si-N-Darl+Di	NF/S-L, 150V, 3A, 15W, B>2000	14b	Nec	2SC4342
2SD1693	Si-N-Darl+Di	NF/S-L, int. Z-Di, 60V, 3A, 15W, B>2000	14h	Nec	—
2SD1694	Si-N	hi-betajo-sat, 60V, 3A, 20W, B>600	14h	Nec	—
2SD1695	Si-N-Darl+Di	int. Z-Di(B→C), 31V, ±2A, B>2000	14h	Nec	—
2SD1696	Si-N-Darl+Di	int. Z-Di(B→C), ±4A, B=10000	14h	Nec	—
2SD1697	Si-N-Darl+Di	NF/S, 100V, ±0,8A, 1W, B>4000	9b	Nec	—
2SD1696	Si-N-Darl+Di	=2SD1897: 0,75W	7c	Nec	—
2SD1699	Si-N-Darl+Di	=2SD1697: SMD	39b	Nec	BST52, 2SD1511
2SD17	Si-N	=2SD15: 150V	23a	Sak	BD245D, BDX11, 2N3442, 2SD731..732,++
2SD170	Ge-N	NF-Tr/E, 25V, 0,5A, 0,2W	2a	Hit	AC127, AC176, AC187, 2SD72, 2SD352
2SD1700	Si-N-Darl+Di	=2SD1697: int. Z-Diode(B→C), 60±10V	9b	Nec	—
2SD1701	Si-N-Darl+Di	=2SD1698: int. Z-Diode(B→C), 60±10V	7c	Nec	—
2SD1702	Si-N-Darl+Di	=2SD1699: int. Z-Diode(B→C), 60±10V	39b	Nec	—
2SD1703	Si-N	NF/S-L, 160/160V, 12A, 120W	18j	Mat	BD745F, 2SC3907, 2SD1047
2SD1704	Si-N	NF/S-L, 170/170V, 15A, 150W	77j	Mat	2SC3261, 2SD1716
2SD1705	Si-N	NF/S-L, 130/80V, 10A, 70W, 20MHz	16c	Mat	(BD245D, 2SC2706, 2SC2637)
2SD1706	Si-N	NF/S-L, 130/60V, 15A, 80W, 20MHz	16c	Mat	(BD745E, 2SC2987A, 2SD1047)
2SD1707	Si-N	NF/S-L, 130/80V, 20A, 100W, 20MHz	16c	Mat	(BD745E, BD249D)
2SD1708	Si-N-Darl+Di	NF/S-L, 120V, 2A, B=6000	14b	Tos	(2SD1376)
2SD1709	Si-N+Di+Rbe≈50	TV-HA, 1500/800V, 5A, 100W	16c	Say	BU508D, 2SC3481..82, 2SC3881..82,++
2SD170A	Ge-N	=2SD170: 32V	2a		AC127, AC176, 2SD352
2SD171-...	Ge-N	S-L, 450..600V, 3,5A, 125W	23a	Son	BUS11(A), BUX47(A), 2SC3156, 2SD640,++
2SD1710	Si-N	TV-HA, 1500/800V, 5A, 50W	16c	Say	BU508AF, 2SC4142..43, 2SD1655..56,++
2SD1711	Si-N+Di+Rbe≈50	TV-HA, 1500/800V, 5A, 100W	16c	Say	BU508DF, 2SC4293..94, 2SD1555..56,++
2SD1712	Si-N	NF/S-L, 100V, 5A, 60W, 20MHz	16c	Mat	(BD245C, 2SD895..896, 2SD1187,++)
2SD1713	Si-N	NF/S-L, 120V, 8A, 70W, 20MHz	16c	Mat	(BD245D, 2SC3161, 2SD896, 2SD1046,++)
2SD1714	Si-N	NF/S-L, 140V, 7A, 60W, 20MHz	16c	Mat	(BD245D, 2SC2706, 2SC2837, 2SD1046,++)
2SD1715	Si-N	NF/S-L, 150V, 9A, 100W, 20MHz	16c	Mat	(BD245D, 2SC2837, 2SD1046..47,++)
2SD1716	Si-N	NF/S-L, 160V, 12A, 120W, 20MHz	16c	Mat	(BD745F, 2SC2987A, 2SD1047, 2SD1703,++)
2SD1717	Si-N	NF/S-L, 160V, 12A, 120W, 20MHz	77j	Mat	2SC3260..3281, 2SD1704, 2SD2029
2SD1716	Si-N	NF/S-L, 160V, 15A, 150W, 20MHz	77j	Mat	2SC3281, 2SD1704
2SD1719	Si-N	hi-Ueb, hi-beta, lo-sat, 100V, 8A, 40W	30j	Mat	—
2SD172	Si-N	NF/S-L, 60V, 10A, 100W	23a	Fui	BD245A, BD315, 2N3055, 2N5677..78,++
2SD1720	Si-N	NF-L, 60V, 5A, 40W, 8MHz	17j	Rhm	BD243B, BD543B, BD951, 2SD813,++
2SD1721	Si-N	NF-Tr/E, 60V, 2A, 1W	9b	Nec	MPS650..651, 2SC3328, 2SD1207,++
2SD1722	Si-N	S-L, lo-sat, 60V, 5A, 20W, 160MHz	≈14h	Say	2SD826, 2SD1685

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2SD1723	Si-N	S-L, lo-sat, 60V, 8A, 20W, 160MHz	≈14h	Say	—
2SD1724	Si-N	S-L, lo-sat, 120V, 8A, 20W, 180MHz	≈14h	Say	—
2SD1725	Si-N	S-L, lo-sat, 120V, 4A, 20W, 180MHz	≈14h	Say	—
2SD1726	Si-N-Darl	NF/S-L, 150/100V, 7A, 25W, B>1500	17c	Fjd	2SD1590..91
2SD1727	Si-N+Di+Rbe≈50	TV-HA, 1500/700V, 1,5A, 60W	16c	Mat	BU706D, 2SC3479, 2SD1290..1291,++
2SD1728	Si-N+Di+Rbe≈50	TV-HA, 1500/700V, 2,5A, 60W	16c	Mat	BU706D, 2SC3479, 2SD1290..1291,++
2SD1729	Si-N+Di+Rbe≈50	TV-HA, 1500/700V, 3,5A, 60W	16c	Mat	BU508D, BU706D, 2SC3480..3482,++
2SD173	Si-N	=2SD172: 100V	23a	Fui	BD245C, BD317, 2N3055, 2N5632..33,++
2SD1730	Si-N+Di+Rbe≈50	TV-HA, 1500/700V, 5A, 100W	16c	Mat	BU508D, 2SC3481..82, 2SC3681, 2SC4291 ++
2SD1731	Si-N+Di+Rbe≈50	TV-HA, 1500/700V, 6A, 100W	16c	Mat	BU508D, 2SC3482, 2SC3681, 2SC4292,++
2SD1732	Si-N+Di	TV-HA, 1500/700V, 7A, 120W	18j	Mat	BU508D, 2SC3682..3683
2SD1733(F5)	Si-N	NF-E-L, 120V, 1A, 10W, 100MHz	30j	Rhm	2SC4134, 2SD1074..75, 2SD1283..1284,++
2SD1734	Si-N	TV-HA, 1500/700V, 1,5A, 40W	17c	Mat	2SD1575, (BU505, BU506, 2SD1390)
2SD1735	Si-N	TV-HA, 1500/700V, 1,5A, 60W	16c	Mat	2SD1542, (BU705, BU706, 2SSC3483)
2SD1736	Si-N	TV-HA, 1500/700V, 2,5A, 60W	16c	Mat	2SD1543, (BU705, BU706, 2SSC3483)
2SD1737	Si-N	TV-HA, 1500/700V, 3,5A, 60W	16c	Mat	BU508AF, 2SD1544, (BU706, 2SC3484)
2SD1736	Si-N	TV-HA, 1500/700V, 5A, 100W	16c	Mat	BU508AF, 2SD1545, (2SSC3485..86)
2SD1739	Si-N	TV-HA, 1500/700V, 6A, 100W	16c	Mat	BU508AF, 2SD1548, (2SC3466, 2SD1497)
2SD174	Si-N	NF/S-L, 60V, 5A, 50W	23a	Fui	BD245A, BDV91, BDX91, 2N5873..74,++
2SD1740	Si-N-Darl	NF/S-L, 150/100V, 5A, 30W, B>700	17c	Fjd	2SD1590, (BDX53F, 2SD1126, 2SD1169,++)
2SD1741(A)	Si-N	=2SD1250(A): 15W	≈30j	Mat	2SD1033, 2SD1557
2SD1742	Si-N	=2SD1252(A): 15W	≈30j	Mat	2SC3386, 2SD1221, 2SD1802
2SD1743	Si-N	=2SD1253(A): 15W	≈30j	Mat	2SC3074, 2SC3518, 2SC3592, 2SD1603
2SD1744	Si-N	=2SD1254: 15W	≈30j	Mat	—
2SD1745	Si-N	=2SD1255: 15W	≈30j	Mat	—
2SD1746	Si-N	=2SD1256: 15W	≈30j	Mat	—
2SD1747(A)	Si-N	=2SD1257(A): 15W	≈30j	Mat	—
2SD1748(A)	Si-N-Darl+Di	=2SD1260(A): 15W	15c(A)	Mat	2SD1222
2SD1749(A)	Si-N-Darl+Di	=2SD1281(A): 15W	15c(A)	Mat	—
2SD175	Si-N	=2SD174: 100V	23a	Fui	BD245C, BDV95, BDX95, 2N5756..59,++
2SD1750(A)	Si-N-Darl+Di	=2SD1262(A): 15W	15c(A)	Mat	—
2SD1751	Si-N	=2SD1480: 15W	≈30j	Mat	2SC3474, 2SD1079, 2SD1281..1262
2SD1752(A)	Si-N	=2SD1445(A): 15W	≈30j	Mat	(2SD1803..1804)
2SD1753	Si-N	=2SD1258: 15W	≈30j	Mat	—
2SD1754(A)	Si-N	=2SD1259(A): 15W	≈30j	Mat	—
2SD1755	Si-N	=2SD1719: 15W	≈30j	Mat	—
2SD1756	Si-N-Darl	NF/S-L, 200/200V, 10A, 40W, B>1500	22c(E)	Hit	—
2SD1757K	Si-N	SMD, lo-sat, 30V, 0,5A, 150MHz	35a	Rhm	2SC3265, 2SC4519
2SD1758(F5)	Si-N	NF-E-L, 40V, 2A, 10W, 100MHz	30j	Rhm	2SC3076, 2SD1078..79, 2SD1601,++
2SD1759(F5)	Si-N-Darl	NF-E-L, 40V, 2A, 10W, B>1000	30j	Rhm	2SD1222, 2SD1817, (BD411..412, MPS-U45)
2SD176	Si-N	NF/S-L, 90V, 10A, 100W	23a	Fui	BD245C, BD317, 2N3055, 2N5632..33,++
2SD1760(F5)	Si-N	NF-E-L, 60V, 3A, 15W, 90MHz	30j	Rhm	2SC3592, 2SC3386, 2SD1221, 2SD1602,++
2SD1761	Si-N	NF-E-L, 60V, 3A, 30W, 8MHz	17c	Rhm	2SC3690, 2SC3746, 2SC3651, 2SD1566,++
2SD1782	Si-N	NF-E, 60V, 3A, 25W, 70MHz	17c	Rhm	2SC3299, 2SC3690..91, 2SC3746, 2SD1913
2SD1783	Si-N	NF-E, 120/120V, 1,5A, 20W, 80MHz	17c	Rhm	2SC3298(A,B), 2SC3364, 2SC3584, 2SC4370
2SD1763A	Si-N	=2SD1763: 160/160V	17c		2SC3298(A,B), 2SC4159, 2SC4370
2SD1764	Si-N-Darl+Di	int. Z-Diode, 60V, 2A, 20W, B>1000	17c(H)	Rhm	(BDT61F, 2SD1413, 2SD1798, 2SD1825,++)
2SD1765	Si-N-Darl+Di	NF/S-L, 100V, 2A, 20W, B>1000	17c(A)	Rhm	2SD1414, 2SD1788, 2SD1828, 2SD2015,++
2SD1786	Si-N	SMD, NF, 40V, 2A, 100MHz	39b	Rhm	2SC2873, 2SD1823, 2SD1766
2SD1767	Si-N	SMD, NF, 60V, 0,7A, 120MHz	39b	Rhm	BCX56, 2SD1005, 2SD1368, 2SD1418..19
2SD1769(S)	Si-N	NF-Tr/E, 100V, 1A, 0,3W, 100MHz	41c	Rhm	BC639, 2SD667, 2SD774, 2SD1618A,++
2SD1769	Si-N-Darl+Di	S-L, 120/120V, 6A, 50W, 100MHz, B>2000	17c(A)	Sak	(BD851, BDT21, BDW73D, BDX53D,++)
2SD177	Si-N	=2SD176: 120V	23a	Fui	BDX11, 2N3442, 2SD551, 2SD732..733,++
2SD1770	Si-N	NF-L, 200/150V, 1A, 25W, 20MHz	17j	Mat	BD239F, 2SC2236B, 2SD387(A), 2SD1136
2SD1770A	Si-N	=2SD1770: 200/160V	17j		BD239F, 2SC2236B, 2SD367(A), 2SD1136
2SD1771(A)	Si-N	=2SD1770(A):	30j	Mat	(2SD1250, BD239F, 2SC2236B), 2SD1138)
2SD1772(A)	Si-N	=2SD1770(A): Iso	17c	Mat	2SC3298B, 2SC4382, 2SD1567, 2SD2337
2SD1773	Si-N-Darl	NF/S-L, 120/120V, 8A, 50W, 20MHz, B>1000	17c(A)	Mat	BD849F, BDT63CF, 2SD1590..91
2SD1774	Si-N	hi-beta, 60V, 2A, 25W, 40MHz, B>500	17j	Mat	2SC3852, 2SD1157, 2SD1943, 2SC1983
2SD1774A	Si-N	=2SD1774: 100V	17j		—
2SD1775(A)	Si-N	=2SD1774(A):	30j	Mat	2SC3474, 2SD1754
2SD1776(A)	Si-N	=2SD1774(A): Iso	17c	Mat	2SD1273(A), 2SD1944, 2SD2092
2SD1777	Si-N	=2SD1676: SMD	44(C-BE)	Hit	—
2SD1778(A)	Si-N	NF/S-L, 60V, 4A, 40W, 8MHz	17j	Rhm	BD243B, BD537, BD536B, BD951,++
2SD1779	Si-N	hi-Ueb, hi-beta, 60V, 2A, 1W, B>800	9b	Nec	—
2SD178	Ge-N	NF, 20V, 0,3A, 0,225W	2a	Mat	AC127, AC176, AC187, 2SD72, 2SD352

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2SD1780	Si-N	=2SD1779: integr. Z-Diode(C→B)	9b	Nec	—
2SD1781K	Si-N	SMD, lo-sat, 40V, 0,6A, 150MHz	35a	Rhm	(BCW65..66, BCX41)
2SD1782K	Si-N	SMD, NF-Tr/E, 80V, 0,7A, 180MHz	35a	Rhm	BCW66, BCX41
2SD1783	Si-N-Darl+Di	int. Z-Diode, 80V, 5A, 30W, B>2000	17c(H)	Rhm	BD645, BD897, BDW23A, BDW63A, ++
2SD1764	Si-N-Darl	=2SD1140: SMD	39b	Tos	2SD1626..1627
2SD1785	Si-N-Darl+Di	NF/S-L, 120V, 6A, 30W, 100MHz, B>2000	17c(A)	Sak	(2SD1336, 2SD1590)
2SD1786	Si-N-Darl	NF-Tr/E, 40V, 2A, 0,9W, B=20000	7c(9mm)	Rhm	2SD1153, 2SD1536, 2SD1661, 2SD1929, ++
2SD1787	Si-N	NF, 50V, 0,5A, 0.4W, 250MHz	9c	Rhm	BC337, BC635, BC637, BC639, ++
2SD1788	Si-N-Darl+Di	S-L, 100/100V, ±4A, 25W, 50MHz, B=1,5k	22c(A)	Shi	—
2SD1789	Si-N-Darl+Di	=2SD1788: 200/200V	15c	Shi	—
2SD178A	Ge-N	=2SD178: 40V	2a		(AC127, AC176, 2SD352)
2SD178B	Ge-N	=2SD178: 80V	2a		—
2SD179	Si-N	S-L 300/300V, 40A, 580W	53b	Nec	—
2SD1790	Si-N-Darl+Di	=2SD1788: int. Z-Diode(B→C), 60V	17c(H)	Shi	—
2SD1791	Si-N-Darl	S-L, 100V, 7A, 30W, 50MHz, B=1,5k..30k	77c(E)	Shi	2SD1793, (2SC4062, 2SD1415, 2SD1830, ++)
2SD1792	Si-N-Darl	=2SD1791: 200/200V	22c(E)	Shi	2SD1794
2SD1793	Si-N-Darl	S-L, 100V, 10A, 50W, 50MHz, B=1,5k..30k	77c(E)	Shi	(2SC4063)
2SD1794	Si-N-Darl	=2SD1793: 200V	22c(E)		—
2SD1795	Si-N-Darl	S-L, 500/400V, 10A, 50W, 50MHz, B>150	22c(E)	Shi	—
2SD1796	Si-N-Darl+Di	int Z-Di, 80V, 4A, 25W, 80MHz, B>2000	15c(I)	Sak	2SD1788, (2SD1790, 2SD1967, 2SD1825)
2SD1797	Si-N-Darl	NF/S-L, 80V, 7A, 30W, B>800	17c(A)	Fjd	2SD1416..17, 2SD1791, 2SD1826
2SD1798	Si-N-Darl	NF/S-L, 300/300V, 0,3A, 15W, B=5000	17c(A)	Hit	2SD1502
2SD1799	Si-N-Darl	NF/S-L, 30V, 3A, 15W, 120MHz, B>4000	30c, 79c(C)	Say	2SC3132, 2SD1222..1223
2SD18	Si-N	=2SD15: 200V	23a	Sak	BD245F, 2SC3263, 2SD555, 2SD751
2SD180	Si-N	NF/S-L, 80V, 5A, 50W, 10MHz	23a	Nec	BD245B, BD313, 2N5758, 2SD895..896, ++
2SD1800	Si-N-Darl	NF/S-L, 80V, 1,5A, 10W, 120MHz, B>4000	30c, 79c(C)	Say	2SD1817, 2SD1980
2SD1801	Si-N	S-L, lo-sat, 60V, 2A, 15W, 150MHz	30j	Say	2SC3303, 2SD1815..1816
2SD1802	Si-N	S-L, lo-sat, 60V, 3A, 15W, 150MHz	30j	Say	2SC3303, 2SD1815..1816
2SD1803	Si-N	S-L, lo-sat, 60V, 5A, 20W, 180MHz	30j	Say	2SC3074, 2SC3303, 2SD1805
2SD1804	Si-N	S-L, lo-sat, 60V, 6A, 20W, 180MHz	30j	Say	—
2SD1805	Si-N	S-L, lo-sat, 60V, 5A, 15W, 120MHz	30j	Say	2SC3074, 2SC3303, 2SD1803
2SD1806	Si-N+Di+R	NF/S-L, 40V, 2A, 15W, 150MHz, Rbe=1kΩ	30j	Say	—
2SD1807	Si-N	=2SD889: 0,3W	40c	Mat	→2SD889
2SD1806(A)	Si-N-Darl	=2SD892(A): 0,3W	40c	Mat	→2SD892(A)
2SD1809	Si-N-Darl	Uni, 80V, 4A, 0,9W, B>2000	14b(A)	Rhm	2SD1153, 2SD1660, 2SD1978, 2SD1961, ++
2SD181	Si-N	NF/S-L, 150V, 15A, 100W, 10MHz	23a	Nec	MJ15015, BD745E, BDW12, 2SC2607..06++
2SD1810	Si-N	NF-Tr/E, 20V, 2A, 0.5W, 80MHz	7c	Rhm	2SC3225, 2SD787..88, 2SD1100, 2SD1207, ++
2SD1811	Si-N	=2SD1810: SMD	39b	Rhm	2SC2883, 2SC2982, 2SC3443, 2SC3439, ++
2SD1812	Si-N	NF-Tr/E, 180V, 1,5A, 0,9W, 80MHz	7c(9mm)	Rhm	2SC4614, 2SD1665A, 2SD1857A
2SD1813	Si-N	NF/S-L, 70V, 4A, 25W	15c	Hit	2SC3691, 2SC3746, 2SC3851, 2SD1586, ++
2SD1814	Si-N-Darl+Di	NF/S-L, 120V, 10A, 30W, B=5000	15c	Hit	2SD1591, (BDT62C, BDX33D, 2SD1607, ++)
2SD1815	Si-N	S-L, lo-sat, 120V, 3A, 20W, 180MHz	35a	Say	—
2SD1816	Si-N	S-L, lo-sat, 120V, 4A, 20W, 180MHz	30j	Say	—
2SD1817	Si-N-Darl+Di	NF/S-L, 80V, 3A, 15W, B>2000	30c(A)	Say	2SD1223, 2SD1520, 2SD1955
2SD1818	Si-N	lo-sat, 80V, 3A, 10W, 120MHz	14h	Nec	2SD1348
2SD1819	Si-N	=2SD601:	35a(2mm)	Mat	2SC4061, 2SC4128, 2SC4155, 2SC4177
2SD1819A	Si-N	=2SD601A:	35a(2mm)		2SC4117, 2SC4141, 2SC4177
2SD181A	Si-N	=2SD181: 250V, 10A	23a		BUX17(A..C), BUX42, 2SC1566, 2SD583, ++
2SD182	Si-N	NF/S-L, 40V, 1A, 10W	2a	Fui	(BD135, BD226, BD507, BD825, ++)
2SD1820	Si-N	=2SD602:	35a(2mm)	Mat	2SC4097, 2SC4118, 2SD1949
2SD1820A	Si-N	=2SD602A:	35a(2mm)		—
2SD1821	Si-N	=2SD814:	35a(2mm)	Mat	—
2SD1821A	Si-N	=2SD814A:	35a(2mm)		—
2SD1822	Si-N	SMD, NF, 25V, 0.5A, 200MHz	35a(2mm)	Mat	(BC817..818, BCW65..66, BCX19..20, ++)
2SD1823	Si-N	=2SD1030:	35a(2mm)	Mat	—
2SD1824	Si-N	=2SD1149:	35a(2mm)	Mat	—
2SD1825	Si-N-Darl+Di	NF/S-L, 70V, 4A, 20W, 20MHz, B=5000	15c(A)	Say	2SD1589, 2SD1788, 2SD1933, 2SD2014, ++
2SD1826	Si-N-Darl+Di	NF/S-L, 70V, 7A, 25W, 20MHz, B=5000	17c	Say	2SC4062, 2SD1415..16, 2SD1791
2SD1827	Si-N-Darl+Di	NF/S-L, 100V, 10A, 30W, 20MHz, B=5000	15c(A)	Say	2SC4063, 2SD1793, (BDT63A, BDW93B, ++)
2SD1828	Si-N-Darl+Di	NF/S-L, 110V, 3A, 20W, 20MHz, B=4000	15c(A)	Say	2SD1785, 2SD2015, (BDW53D, BDW63D, ++)
2SD1829	Si-N-Darl+Di	NF/S-L, 110V, 5A, 25W, 20MHz, B=4000	15c(A)	Say	2SD1785, 2SD2025, (BD651, BDW63D, ++)
2SD163	Si-N	=2SD182: 100V	2a	Fui	(BD139, BD230, BD529, BD829, ++)
2SD1830	Si-N-Darl+Di	NF/S-L, 110V, 6A, 30W, 20MHz, B=4000	15c	Say	2SD1591, 2SD2025, (BD651, BDW73D, ++)
2SD1631	Si-N	hi-Ueb, hi-beta, 100V, 12A, 60W, 30MHz	16c	Mat	—
2SD1832	Si-N	NF/S-L, 80V, 5A, 30W, 8MHz	17c	Rhm	2SC3691, 2SC3746, 2SD1588, 2SD1940
2SD1833	Si-N	NF/S-L, 100V, 7A, 30W, 5MHz	17c	Rhm	2SC3892, 2SD1411, 2SD1588

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2SD1834	Si-N-Darl	SMD, 60V, 1A, B>2000	39b(C)	Rhm	BST50..52, 2SD1470, 2SD1511
2SD1835	Si-N	S, Io-sat, 60V, 2A, 150MHz, 60/580ns	7c	Say	2SC3328
2SD1836	Si-N-Darl+Di	int Z-Di(B→C), 60V, 2A, 20W, B=4000	15c(I)	Say	2SC3986, 2SD1413, 2SC1983, 2SD205t
2SD1837	Si-N-Darl+Di	int Z-Di, 50V, 3A, 20W, 20MHz, B=4000	15c(I)	Say	2SC3987, 2SD1413, 2SD1825, 2SD1987
2SD1839	Si-N-Darl+Di	int Z-Di, 50V, 5A, 25W, 20MHz, B=4000	15c(I)	Say	2SD1790, 2SD1798, 2SD1825, 2SD1987
2SD1839	Si-N-Darl+Di	S-L, 365/365V, 5A, 80W, B=2000	16c	Mat	—
2SD184	Si-N	NF/S-L, 60V, 1,5A, 25W, -/3,5µs	2a	Ful	(BD185, BD233, BD239A, BD241A,++)
2SD1840	Si-N	NF/S-L, Io-sat, 110V, 15A, 100W	18j	Say	—
2SD1841	Si-N	NF/S-L, Io-sat, 110V, 25A, 120W	18j	Say	—
2SD1842	Si-N	NF/S-L, Io-sat, 110V, 40A, 150W	18j	Say	—
2SD1843	Si-N-Darl+Di	Uni, int Z-Diode, 60V, ±1A, 1W, B>2000	14b(H)	Nec	—
2SD1843A	Si-N-Darl+Di	=2SD1843: 60V	9b		—
2SD1844	Si-N+Di+Rbe≈50	TV-HA, 1500/700V, 1,5A, 60W	16c	Mat	2SD1553, BU706DF, (2SD1728, 2SD1290..91)
2SD1845	Si-N+Di+Rbe≈50	TV-HA, 1500/700V, 2,5A, 60W	16c	Mat	2SD1553, BU706DF, (2SC3479, 2SD1290..91)
2SD1846	Si-N+Di+Rbe≈50	TV-HA, 1500/700V, 3,5A, 60W	16c	Mat	2SD1554, 2SD1650, BU706DF, (2SD1290..91)
2SD1847	Si-N+Di+Rbe≈50	TV-HA, 1500/700V, 5A, 100W	16c	Mat	BU506DF, 2SC4122, 2SC4291, 2SD1555..56+
2SD1846	Si-N+Di+Rbe≈50	TV-HA, 1500/700V, 6A, 100W	16c	Mat	BU508DF, 2SC4122, 2SC4292, 2SD1556,++
2SD1849	Si-N+Di+Rbe≈50	TV-HA, 1500/700V, 7A, 120W	16c	Mat	BU508DF, 2SC4123, (2SC3482..83,++)
2SD185	Si-N	=2SD184: 100V	2a	Ful	(BD169, BD237, BD239C, BD241C,++)
2SD1850	Si-N	TV-HA, 1500/700V, 7A, 120W	16c	Mat	BU508AF, 2SC3884A, 2SC3895, 2SD1547
2SD1851	Si-N-Darl	=2SD1852: SMD	35a(C)	Say	BCV47
2SD1852	Si-N-Darl	Uni, 60V, 0,2A, 0,3W, B>5000	40c(C)	Say	MPS-A28..29
2SD1853	Si-N-Darl+Di	Uni, 60V, 1,5A, 0,7W, B>2000	7c	Say	2SD1153, 2SD1660
2SD1854	Si-N-Darl+Di	=2SD1853: 1W	7c(9mm)	Say	2SD1153, 2SD1660, 2SD1978, 2SD1981
2SD1855(A)	Si-N	NF-L, 60V, 4A, 30W, 8MHz	17c	Rhm	2SC3851, 2SC3691, 2SD1408, 2SD2000,++
2SD1856	Si-N-Darl+Di	int. Z-Di(B→C), 60V, 5A, 25W, B>2000	15c(I)	Rhm	(2SD1417, 2SD1569, 2SD1595, 2SD1828,++)
2SD1857	Si-N	=2SD1685(M): Pins=14mm	9c	Rhm	→2SD1857
2SD1858	Si-N	=2SD1225(M): Pins=14mm	9c	Rhm	→2SD1225
2SD1859	Si-N	=2SD1226(M): Pins=14mm	9c	Rhm	→2SD1226
2SD186	Ge-N	NF, 25V, 0,15A, 0,2W	2a	Say	AC127, AC176, AC187, 2SD30, 2SD72
2SD1860	Si-N	=2SD1228(M): Pins=14mm	9c	Rhm	→2SD1228
2SD1861	Si-N-Darl	=2SD1536(M): Pins=14mm	9c	Rhm	→2SD1536
2SD1862	Si-N	=2SD1227(M): Pins=14mm	9c	Rhm	→2SD1227
2SD1863	Si-N	=2SD1293(M): Pins=14mm	9c	Rhm	→2SD1293
2SD1864	Si-N	=2SD1507(M): Pins=14mm	9c	Rhm	→2SD1507
2SD1865	Si-N	=2SD1469M: Pins=14mm	9c	Rhm	→2SD1469M
2SD1866(M)	Si-N-Darl+Di	=2SD1661(M): Pins=14mm	9c(H)	Rhm	→2SD1861
2SD1867(M)	Si-N-Darl+Di	=2SD1660(M): Pins=14mm	9c(A)	Rhm	→2SD1660
2SD1866	Si-N	NF/Vid, 160/160V, 0,1A, 0,9W, 140MHz	7c(9mm)	Hit	BF391..393, 2SC3248, 2SC3487,++
2SD1869	Si-N	=2SD1886: 200/200V	7c(9mm)	Hit	BF391..393, 2SC3467..3469,++
2SD187	Ge-N	NF, 25V, 0,15A, 0,2W	2a	Say	AC127, AC176, AC187, 2SD30, 2SD72
2SD1870	Si-N	SMD, hi-beta, 30V, 1A, B=1k..3k	39b	Hit	2SC3727, 2SD1950
2SD1871	Si-N	NF/S-L, 40V, 2A, 10W	30j	Mit	2SD1078..79, 2SD1601..02, (BD515,++)
2SD1872	Si-N	NF/S-L, 60V, 1,5A, 10W	30j	Mit	2SD1079, 2SD1221, 2SD1601..02, (BD517+)
2SD1873	Si-N	NF/S-L, 110V, 0,8A, 10W	30j	Mit	2SD1074..75, 2SD1283..84, (BD529)
2SD1874	Si-N	NF/S-L, 130V, 0,8A, 10W	30j	Mit	2SC2983, 2SC4027, 2SD1060..82, 2SD1220,
2SD1875	Si-N-Darl+Di	NF/S-L, 50V, 1,5A, 10W, B=10000	14b	Rhm	(BD677, BD777, 2N6039..39, 2SD1378,++)
2SD1876	Si-N+Di+Rbe≈50	TV-HA, 1500/800V, 3A, 50W	19c	Say	BU706DF, 2SD1553..54, 2SD1650, 2SD2089
2SD1877	Si-N+Di+Rbe≈50	TV-HA, 1500/800V, 4A, 50W	19c	Say	BU706DF, 2SD1554..55, 2SD1851, 2SD2089
2SD1878	Si-N+Di+Rbe≈50	TV-HA, 1500/800V, 5A, 60W	18c	Say	BU508DF, 2SD1555, 2SD2095, 2SD2125
2SD1879	Si-N+Di+Rbe≈50	TV-HA, 1500/800V, 6A, 60W	19c	Say	BU508DF, 2SC4294, 2SD1556, 2SD2125
2SD186	Si-N	NF/S-L, 100V, 7A, 60W, 10MHz	23a	Nip	BD245C, BD317, 2N5756, 2SD895..898,++
2SD1880	Si-N+Di+Rbe≈50	TV-HA, 1500/800V, 8A, 70W	16c	Say	BU508DF, 2SC3693A, 2SC4124, 2SC4531
2SD1881	Si-N+Di+Rbe≈50	TV-HA, 1500/800V, 10A, 70W	16c	Say	BU2520AF, 2SC4125, 2SC4531
2SD1662	Si-N	TV-HA, 1500/800V, 3A, 50W	16c	Say	BU706F, 2SD1553, 2SD1653, (2SC3483..84,+)
2SD1883	Si-N	TV-HA, 1500/800V, 4A, 50W	16c	Say	BU706F, 2SD1544, 2SD1654, (2SC3454..86,+)
2SD1884	Si-N	TV-HA, 1500/800V, 5A, 60W	16c	Say	BU508AF, 2SC4142, 2SD1545, 2SD1655,++
2SD1885	Si-N	TV-HA, 1500/800V, 6A, 60W	16c	Say	BU508AF, 2SC4143, 2SD1546, 2SD1656
2SD1886	Si-N	TV-HA, 1500/800V, 8A, 70W	16c	Say	BU508AF, 2SC3898, (BU908, 2SC3687,++)
2SD1887	Si-N	TV-HA, 1500/800V, 10A, 70W	18c	Say	BU2520AF, 2SC3997, (2SC3688)
2SD1886	Si-N-Darl+Di	NF/S-L, 120/120V, 8A, 40W, B=5000	17c(A)	Rhm	(BD651, BDT21, BDW83D, BDW73D,++)
2SD1869	Si-N-Darl+Di	=2SD1888: Iso, 30W	17c(A)	Rhm	2SD1765, 2SD2025, 2SD1590
2SD189	Si-N	NF/S-L, 60V, 5A, 50W, 12MHz	23a	Mat	BD245B, BDV93, BDX93, 2N5832..33,++
2SD1890	Si-N-Darl	NF/S-L, 150V, 6A, 35W, 20MHz, B>5000	22c(A)	Mat	—
2SD1891	Si-N-Darl	NF/S-L, 110V, 4A, 40W, 20MHz, B>5000	22c(A)	Mat	—
2SD1892	Si-N-Darl	NF/S-L, 120V, 5A, 45W, 20MHz, B>5000	22c(A)	Mat	—

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2SD1893	Si-N-Darl	NF/S-L, 130V, 6A, 50W, 20MHz, B>5000	22c(A)	Mat	—
2SD1894	Si-N-Darl	NF/S-L, 160V, 7A, 70W, 20MHz, B>5000	22c(A)	Mat	—
2SD1895	Si-N-Darl	NF/S-L, 160V, 6A, 100W, 20MHz, B>5000	22c(A)	Mat	—
2SD1896	Si-N	NF/S-L, 100V, 5A, 40W, 8MHz	17j	Rhm	BD243C, BD539C, BD543C, BD953, ++
2SD1897	Si-N	=2SD1896: Iso, 30W	17c	Rhm	2SC3691, 2SD1407, 2SD1588, 2SD1940, ++
2SD1898	Si-N	SMD, Uni, 100V, 1A, 100MHz	39b	Rhm	BCX56, 2SD1005, 2SD1386, 2SD1418..19
2SD1899(Z)	Si-N	NF/S-L, 60V, 3A, 10W, 120MHz	30j	Nec	2SC3386, 2SD1221, 2SD1802, 2SD1815..16++
2SD189A	Si-N	=2SD189: 100V	23a		BD245C, BDV95, BDX95, 2N5632..33, ++
2SD19	Ge-N	NF-Tr/E, 25V, 0,3A, 0,15W, B=31	2a	Nec	AC127, AC176, AC187, 2SD72, 2SD352
2SD190	Si-N	S/Vid-L, 300V, 0,1A, 4W, 25MHz	≈22	Hit	2SC1505..1507, 2SC1755..1757, 2SC1819, ++
2SD1900	Si-N-Darl	NF/S-L, 60V, 4A, 25W, B=5000	15c	Hit	2SD1790, 2SD1796, 2SD1825, 2SD1967, ++
2SD1901	Si-N-Darl	NF/S-L, 60V, 6A, 25W, B=5000	15c	Hit	2SD1418..17, 2SD1793, 2SD1826..27, ++
2SD1902	Si-N	NF-L, 60V, 3A, 30W, 40MHz	30c	Say	2SD1251..52, (BD241A, BD535, BD539A, +)
2SD1903	Si-N	S-L, Io-sat, 80V, 6A, 30W, 120MHz	30c	Say	—
2SD1904	Si-N	S-L, Io-sat, 60V, 5A, 30W, 30MHz	30c	Say	2SD1906, 2SD2198, 2SD2200
2SD1905	Si-N	S-L, Io-sat, 80V, 7A, 40W, 10MHz	30c	Say	2SD1907, 2SD2199, 2SD2201
2SD1906	Si-N	S-L, Io-sat, 90V, 5A, 30W, 20MHz	30c	Say	2SD1907, 2SD2200..01
2SD1907	Si-N	S-L, Io-sat, 90V, 7A, 40W, 20MHz	30c	Say	2SD2201
2SD1908	Si-N	HV, 330/150V, 7A, 50W, 40MHz	30c	Say	(BU406..408, 2SC3173, 2SD884..885, ++)
2SD1909	Si-N-Darl	NF/S-L, 500/300V, 6A, 45W, B>500	17c	Mat	2SD1409
2SD191	Ge-N	NF, 30V, 0,15A, 0,15W	2a	Tos	AC127, AC176, 2SD352
2SD1910	Si-N+Di+Rbe≈50	TV-HA, 1500/600V, 3A, 40W	16c	Hit	2SD1544, 2SD1653, BU706DF, (2SC3479, ++)
2SD1910FI	Si-N+Di	=2SD1910:	16c	Tho	2SD1544, 2SD1653, BU706DF, (2SC3479, ++)
2SD1911	Si-N+Di+Rbe≈50	TV-HA, 1500/600V, 5A, 50W	16c	Hit	BU508DF, 2SC4293, 2SC4122, 2SD1651, ++
2SD1912	Si-N	NF-L, 80V, 3A, 30W, 100MHz	17j	Say	2SC3252, (BD241A, BD535, BD539A, ++)
2SD1913	Si-N	=2SD1912: Iso, 20W	17c	Say	2SC3299, 2SC3691, 2SC3746
2SD1914	Si-N-Darl+Di	Tr-L, 100V, 2A, 10W, B=2k..30k	14b	Say	(2SD1376, 2SD1953)
2SD1915	Si-N	hi-Ueb(25V), hi-beta, 60V, 0,3A, B>500	40c	Mat	2SC3615, (2SC3247, 2SD1582)
2SD1916	Si-N-Darl+Di	Uni, 60V, 2A, 1W, B=5000	9c	Tos	2SD1153, 2SD1809, 2SD1866, 2SD1853, ++
2SD1917	Si-N-Darl	int Z-Di(B→C), 60V, 1A, B=20000	14b(A)	Mat	—
2SD1918(F5)	Si-N	NF/S-L, 160/160V, 1,5A, 10W, 80MHz	30j	Rhm	2SC2983, 2SC4027, 2SD1080..82
2SD1919	Si-N	=2SD1055: Pins=14mm	9c	Rhm	→2SD1055
2SD192	Ge-N	NF, 30V, 0,15A, 0,15W	2a	Tos	AC127, AC176, 2SD352
2SD1920	Si-N	=2SD1489: Pins=14mm	9c	Rhm	→2SD1489
2SD1921	Si-N	=2SD1737: Pins=14mm	9c	Rhm	→2SD1737
2SD1922	Si-N+Di	int.Z-Di(C→B), 25V, 0,6A, 0,9W, B=600	7c(9mm)	Hit	—
2SD1923	Si-N-Darl+Di	NF/S-L, 80V, 4A, 25W, B=5000	15c	Hit	2SD1539, 2SD1923, 2SD1933, 2SD2014
2SD1924	Si-N-Darl+Di	NF/S-L, 80V, 6A, 25W, B=5000	15c	Hit	2SC4062, 2SD1415..18, 2SD1793
2SD1925	Si-N-Darl+Di	NF/S-L, 120V, 3A, 25W, B=5000	15c	Hit	2SD1736, 2SD2015, (BDW53D, BDW63D, ++)
2SD1926	Si-N-Darl	NF/S-L, 200/200V, 10A, 30W, B=5000	15c	Hit	2SD1794, (2SD1756)
2SD1927	Si-N-Darl+Di	NF/S-L, 120/120V, 6A, 25W, B=5000	15c	Hit	2SD1590, (BD651, BDW73D, BDX53D, ++)
2SD1928	Si-N-Darl+Di	S-L, 100/100V, ±6A, 25W, B>2000	17c	Nec	BD647F, 2SC4062, 2SD1415, 2SD1791
2SD1929	Si-N-Darl+Di	int. Z-Di(B→C), 60V, 2A, 1,2W, B=5000	14b(H)	Rhm	2SD1354, 2SD1931
2SD193	Ge-N	NF, 36V, 0,4A, 0,25W, -/4,7µs	2a	Tos	AC127, AC176, 2SD352
2SD1930	Si-N-Darl	Uni, 100V, 2A, 1,2W, B=5000	7c(9mm)	Rhm	2SD1973, 2SD1931
2SD1931	Si-N-Darl+Di	int Z-Di(B→C), 60V, 2A, 1,2W, B=10000	14b(H)	Rhm	—
2SD1932	Si-N-Darl+Di	NF/S-L, 80/60V, 4A, 35W, B=3000	17c(A)	Rhm	BD717, BDW32B, BDW53B, BDW63B, ++
2SD1933	Si-N-Darl+Di	=2SD1932: Iso, 30W	17c(A)	Rhm	BD847F, 2SD1539, 2SD1733, 2SD1923, ++
2SD1934	Si-N	=2SD965: 1W	7c(9mm)	Mat	2SD966, 2SD1244, 2SD2249, 2SD1961
2SD1935	Si-N	=2SD1936: SMD	35a	Say	2SC3285
2SD1936	Si-N	NF, Io-sat, 15V, 0,6A, 0,3W, 200MHz	40c	Say	2SD1012, 2SD1616, 2SD2322
2SD1937	Si-N	=2SD1211:	7c(9mm)	Mat	2SC2235, 2SD667(A), 2SD1816A, 2SD1312, ++
2SD1938	Si-N	=2SD1915: SMD	35a	Mat	—
2SD1939	Si-N-Darl+Di	S, 150/60V, ±1,6A, 0,75W, B>2000	7c	Nec	2SD1579, 2SD1659
2SD194	Ge-N	NF, 32V, 0,4A, 0,25W	2a	Tos	AC127, AC176, 2SD352
2SD1940	Si-N	NF/S-L, 100V, 6A, 25W, 15MHz	17c	Say	2SC3692, 2SD1411, 2SD1533
2SD1941	Si-N	TV-HA, 1500/650V, 6A, 50W	77c	Hit	BU503AF, 2SC4143, 2SD1545..47, 2SD1652, +
2SD1942	Si-N	NF, 40V, 2A, 1,2W	7c(9mm)	Rhm	2SC3323, 2SC4145, 2SD1148, 2SD1207, ++
2SD1943	Si-N	hi-beta, 80V, 3A, 40W, 50MHz, B>400	17j	Rhm	(2SD1157, 2SC1933)
2SD1944	Si-N	=2SD1943: Iso, 30W	17c	Rhm	2SD1273, 2SD2092, 2SD2156, 2SD2375, ++
2SD1945	Si-N	NF/S-L, 1000/1000V, 0,5A, 20W	30j	Hit	(BUX87)
2SD1946	Si-N	SMD, hi-beta, 15V, 1A, B=600	39b	Hit	2SC4390, 2SD1870
2SD1947	Si-N+Di	hi-beta, Io-sat, 100V, 10A, 70MHz, B>500	17c	Tos	2SC4024
2SD1948	Si-N+Di	hi-beta, Io-sat, 60V, 5A, 110MHz, B>500	17c	Tos	2SD2075..2076
2SD1949	Si-N	=2SD1484K:	35a(2mm)	Rhm	—
2SD195	Ge-N	NF/S, 20V, 0,05A, 0,15W	2a	Fui	AC127, 2SD30

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2SD1950	Si-N	SMD, hi-beta, hi-Ueb, 30V, 2A, B=1500	39b	Nec	—
2SD1951	Si-N	Uni, lo-sat, 20V, 3A, 0,75W, 140MHz	7c	Nec	2SC4487, 2SD879, 2SD1617, 2SD1347
2SD1952	Si-N	=2SD1951 SMD	39b	Nec	2SD1119, 2SD1620, 2SD1624
2SD1953	Si-N-Darl+Di	NF/S-L, 120V, 1,5A, 10W, B=8000	14b (A)	Say	2SD1376
2SD1955	Si-N-Darl+Di	NF/S-L, 110V, 3A, 10W, 20MHz, B>1500	30c (A)	Say	2SC4339
2SD1956	Si-N+Di	NF/S-L, 120V, 7A, 40W, 40MHz, B=300	17j	Rhm	—
2SD1957	Si-N+Di	=2SD1956 Iso, 30W	17c	Rhm	—
2SD1956	Si-N	Sw, S-L, 200/60V, 4,5A, 30W, 10MHz	17c	Say	(2SC4153)
2SD1959	Si-N	S-L, TV-HA, 1400/650V, 10A, 50W	18c	Say	BU2520AF, 2SD1546
2SD196(A)	Si-N	NF/S-L, 100V, 10A, 125 150W	38a	Fui	(BD249C, BD745C, 2SD1049)
2SD1960	Si-N	NF, lo-sat, 30V, 5A, 0,75W, 170MHz	7c	Rhm	2SC4482, 2SD1145
2SD1961	Si-N	NF, Strobo, 50V, 5A, 1,2W, 150MHz	7c(9mm)	Rhm	2SC3671, 2SC4482, 2SD1145, 2SD2097, ++
2SD1962(M)	Si-N	=2SD1961 0,3W, M=1W	9c	Rhm	2SC3671, 2SC4482, 2SD1145, 2SD2097, ++
2SD1963	Si-N	SMD, Blitzg./Strobo, 50V, 3A, 150MHz	39b	Rhm	2SC4521, 2SD1624
2SD1964	Si-N	NF/S-L, 130/80V, 15A, 50W, 20MHz	17c	Mat	2SC3699
2SD1965	Si-N	NF/S-L, 120V, 1A, 5W	≈14b	Rhm	—
2SD1966	Si-N	NF/S-L, 80V, 0,7A, 5W	≈14b	Rhm	—
2SD1967	Si-N-Darl	NF/S-L, 40V, 2A, 5W, B=20000	14h	Rhm	—
2SD1968	Si-N	NF/S-L, 40V, 2A, 5W	14b	Rhm	2SC3422, 2SD1189, 2SD1682
2SD1969	Si-N	50V, 2A, 0,5W	62b	Rhm	—
2SD197(A)	Si-N	≠2SD196: 130V	38a	Fui	(2SD1049)
2SD1970	Si-N-Darl+Di	int Z-Diode(B→C), 24V, 2A, 10W, B>7000	14h	Hit	—
2SD1971	Si-N	S-L400/400V, 0,5A, 5W, 55MHz	14h	Mat	2SC2899
2SD1972	Si-N	lo-sat, 60V, 3A, 15W, 100MHz, hi-B>250	17c	Mit	2SD2092, 2SD2127, 2SD1948
2SD1973	Si-N	hi-beta, 80V, 2A, B=1000	14b	Mat	—
2SD1974	Si-N	=2SD1922: SMD	39b	Hit	—
2SD1975	Si-N	NF/S-L180V, 15A, 150W, 20MHz	17j	Mat	2SC3281, 2SD1704, 2SD1718
2SD1976	Si-N-Darl+Di	int. Z-Diode, 300/300V, 6A, 40W, B>500	17j	Hit	2SD991, 2SD1071, 2SD1088, 2SD1113, ++
2SD1977	Si-N	NF/S-L, 120V, 8A, 65W, 60MHz	18c	Nec	2SC4366, 2SC4689, (BD245C, BD545D, ++)
2SD1978	Si-N-Darl+Di	NF, 120V, 1,5A, 0,9W, B=2k 30k	7c(A)	Hit	2SD1579, 2SD1659, 2SD2067, 2SD2213
2SD1979	Si-N	=2SD1915: SMD	35a(2mm)	Mat	(2SC4366)
2SD198	Si-N	S-L, 300V, 1A, 25W(Tc=75°), 45MHz	23a	Mat	BU126, 2SC2809, 2SD632
2SD1980	Si-N-Darl+Di	NF/S-L, 100V, 2A, 10W, B=3000	79c(A)	Rhm	2SD1223, 2SD1520
2SD1961	Si-N-Darl+Di	NF, 100V, 2A, 1W, B=7000	7c(9mm)	Say	2SC1879, 2SD1660, 2SD1667, 2SD1978
2SD1982	Si-N-Darl+Di	S-L, 300/300V, 6A, 80W, B=2000	18j	Hit	2SD1461
2SD1963	Si-N-Darl+Di	int Z-Di(B→C), 80V, 1,5A, 20W, B=10000	17c	Rhm	2SD2051
2SD1984	Si-N	NF, hi-beta, 30V, 1A, 0.9W, B=1500	7c(9mm)	Hit	2SC3070, 2SC3225, 2SC3726
2SD1985(A)	Si-N	=2SD1252(A) 25W	17c	Mat	BD935F, 2SC3851..52, 2SD1585, 2SD1913
2SD1986	Si-N-Darl	NF/S-L, 80V, 4A, 35W, B=5000	17c(A)	Rhm	BD715, BDW23A, BDW53A, BDW63A, ++
2SD1967	Si-N-Darl	≠2SD1966: Iso, 30W	17c(A)	Rhm	2SD1595, 2SD1790, 2SD1796, 2SD1933, ++
2SD1986	Si-N-Darl+Di	int. Z-Di(B→C), 45V, 2A, 25W, B=3000	17c	Rhm	BD713, BDW23, BDW53, BDW63, ++
2SD1989	Si-N-Darl+Di	=2SD1968: Iso, 20W	17c	Rhm	BDT81F, 2SD1790, 2SD1796, 2SD1967, ++
2SD199	Si-N	S-L, 800V, 0,25A, 25W(Tc=75°), 7MHz	23a	Mat	2SC3151
2SD1990	Si-N	NF/S-L, 80V, 4A, 35W, 80MHz	17j	Mat	BDV10..12, 2SC3253, 2SC3256
2SD1991	Si-N	=2SD636: Pins=14mm	9c	Mat	→2SD636
2SD1991A	Si-N	=2SD637: Pins=14mm	8c		→2SD637
2SD1992	Si-N	→2SD936: Pins=14mm	9c	Rhm	→2SD638
2SD1992A	Si-N	→2SD939: Pins=14mm	8c		→2SD639
2SD1993	Si-N	=2SD661A: Pins=14mm	9c	Mat	→2SD661A
2SD1994(A)	Si-N	=2SD973(A): Pins=14mm	9c	Mat	→2SD973(A)
2SD1995	Si-N	=2SD1010: Pins=14mm	9c	Mat	→2SD1010
2SD1996	Si-N	=2SD1302: Pins=14mm	9c	Mat	→2SD1302
2SD1997	Si-N+Di+R	Motor-Tr, 40V, 3A, Rb=180Ω, Rbe=800Ω	39b	Say	—
2SD1998	Si-N+Di+R	Motor-Tr, 40V, 3A, Rb=0Ω, Rbe=800Ω	39b	Say	—
2SD1999	Si-N+Di+R	Motor-Tr, 30V, 4A, Rb=0Ω, Rbe=1,5kΩ	39b	Say	—
2SD20	Ge-N	=2SD19: B=50	2a	Nec	AC127, AC178, AC187, 2SD72, 2SD352
2SD200(A)	Si-N	TV-HA, 1500V, 2,5A, 10W(Tc=90°)	23a	Mat	BU205..206, 2SC1922, 2SD575, 2SD618, ++
2SD2000	Si-N	=2SD1990: Iso	17c	Mat	2SC3691, 2SC3746, 2SC4549, 2SC4596
2SD2001	Si-N+Di	S-L, TV-HA, 1500/700V, 1,5A, 40W	17c	Mat	BU505DF
2SD2002	Si-N	S-L, TV-HA, 1500/800V, 5A, 50W	19c	Say	BU508AF, 2SC3481..82, 2SC3661, 2SD1731
2SD2004	Si-N	Uni, 160/180V, 1,5A, 1,2W, 80MHz	78b	Rhm	2SC2983, 2SC4027, 2SD1916, 2SA2122..23
2SD2005	Si-N	lo-sat, 40V, 1A, 1,2W, 150MHz	78b	Rhm	2SC3076, 2SD1801
2SD2006	Si-N	lo-sat, 80V, 0,7A, 1,2W, 120MHz	78b	Rhm	—
2SD2007	Si-N	lo-sat, 40V, 2A, 1,2W, 100MHz	78b	Rhm	2SC3076, 2SD1801
2SD2008	Si-N	lo-sat, 120/80V, 1A, 1,2W, 100MHz	78b	Rhm	2SC4135
2SD2009	Si-N-Darl	NF, 80/80V, 1A, 1,2W, B>2000	14b(A)	Rhm	2SC2671, 2SC4500, 2SD1596, 2SD1800

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2SD201	Si-N	NF/S-L, 90V, 6A, 50W, -/4µs	23a	Sak	BD245C, BDV95, BDX95, 2N5632..33, ++
2SD2010	Si-N-Darl+Di	Z-Di(B→C), 60/60V, 2A, 1,2W, B>1000	14b(H)	Rhm	—
2SD2011	Si-N-Darl+Di	=2SD1638:	14b	Rhm	2SD1955, 2SD1960, 2SD2410
2SD2012	Si-N	NF-L, 60V, 3A, 25W, 3MHz, B=100320	17c	Tos	BD935F, 2SD1406, 2SD1585, 2SD1913, ++
2SD2014	Si-N-Darl+Di	NF/S-L, 120/60V, 4A, 25W, 75MHz, B>2000	22c(A)	Sak	2SD1336, 2SD1765
2SD2015	Si-N-Darl+Di	NF/S-L, 150/120V, 4A, 25W, 40MHz, B>2000	22c(A)	Sak	2SD1590, 2SD1769
2SD2016	Si-N-Darl+Di	NF/S-L, 250/200V, 3A, 25W, 90MHz, B>000	15c(K)	Sak	2SD1789
2SD2017	Si-N-Darl+Di	S-L, 300/250V, 6A, 35W, B>2000	15c(K)	Sak	2SD1410, (2SD1086, 2SD1113, 2SD1976, ++)
2SD2018	Si-N-Darl+Di	inL Z-Di, 60V, 1A, 5W, 150MHz, B>6500	14b(H)	Mat	—
2SD2019	Si-N-Darl+Di	NF-L, 150V, 1,5A, 10W, B>5000	14b	Hit	2SC4342, 2SD985. 986
2SD202	Si-N	=2SD201: 110V	23a	Sak	BD245C, 2N5633, 2SC2681, 2SD716, ++
2SD2020	Si-N	NF/S-L, 150V, 2A, 40W	17j	Rhm	BD239D, 2SC1669, 2SC2073, 1SD1138, ++
2SD2021	Si-N	=2SD2020: Iso, 30W	17c	Rhm	2SC3566..67, 2SC3895, 2SD1587
2SD2022	Si-N-Darl+Di	int.Z-Di(B→C), 60V, 1,5A, 25W, B=3000	17c	Rhm	BD715, BDW23A, BDW53A, BDW63A, ++
2SD2023	Si-N	NF/S-L, 60V, 3A, 40W, 6MHz	17j	Rhm	BD241B, BD537, BD539B, BD951, ++
2SD2024	Si-N-Darl+Di	NF/S-L, 100V, 6A, 40W, B=10000	17c(A)	Rhm	—
2SD2025	Si-N-Darl+Di	=2SD2024: Iso, 30W	17c(A)	Rhm	—
2SD2026	Si-N-Darl	SMD, 30V, 0,3A, 200MHz, B=30000	35a	Rhm	2SD1478
2SD2027	Si-N	NF/S-L, 60V, 3A, 30W, 6MHz	17j	Say	BD241A, BD353, BD539A, BD935, ++
2SD2028	Si-N	SMD, int. Z-Di(C→B), 8V, 0,7A	35a	Say	—
2SD2029	Si-N	S-L, 160/160V, 12A, 120W, 20MHz	77j	Mat	2SC3260..3261, 2SD1717
2SD203	Si-N	=2SD201: 130V	23a	Sak	BD245D, BDX11, 2N4346, 2N5634, 2SD551, ++
2SD2030	Si-N	=2SD1668: 0,4W	7c	Hit	BF420A, BF422A, BF391, 2SC3245A, ++
2SD2031	Si-N	=2SD1869: 0,4W	7c	Hit	BF420A, BF422A, BF391, 2SC3467, ++
2SD2032	Si-N-Darl+Di	NF/S-L, 80V, 4A, 20W, B=3000	17c(A)	Rhm	2SD1233, 2SD1520
2SD2033	Si-N	NF/S-L, 120V, 1,5A, 1,8W, 60MHz	78c	Rhm	(2SC2690, 2SD1563, 2SD1684)
2SD2033A	Si-N	=2SD2033: 160V	78c	Rhm	(2SC2690A, 2SC3117, 2SD1563A)
2SD2034	Si-N	NF/S-L, 60V, 3A, 25W	78c	Rhm	—
2SD2035	Si-N	NF/S-L, 60V, 4A, 1,6W, 6MHz	78c	Rhm	(BD441, BD767, BD769, MJE240..242)
2SD2036	Si-N	NF/S-L, 100V, 7A, 1,6W, 5MHz	78c	Rhm	—
2SD2037	Si-N	NF/S-L, 60V, 6A, 1,6W, 90MHz	78c	Rhm	(BD787, BD789, 2SD1506, 2SD1618, ++)
2SD2038	Si-N	NF/S-L, 60V, 5A, 1,6W, 8MHz	78c	Rhm	—
2SD2039	Si-N-Darl+Di	NF/S-L, 100V, 2A, ,8W, B-4000	17c(A)	Rhm	(2SD985..68, 2SD1376, 2SD1953)
2SD204	Si-N	NF/S-L, 60V, 0,7A, 0,7W, 9W(Tc=25°)	2a	Nec	(BD137, BD226, BD517, BD525, ++)
2SD2040	Si-N	NF/S-L, 100V, 5A, 1,8W, 8MHz	78c	Rhm	—
2SD2041	Si-N-Darl+Di	int. Z-Di(B→C), 60V, 2A, B=4000	17c(H)	Rhm	—
2SD2042	Si-N-Darl+Di	int. Z-Di(B→C), 60V, 5A, B=10000	15c(I)	Rhm	—
2SD2043	Si-N-Darl+Di	NF/S-L, 120V, 6A, B=10000	17c(A)	Rhm	—
2SD2044	Si-N	NF/S-L, hi-beta, 60V, 3A, B=400..2000	78c	Rhm	—
2SD2045	Si-N-Darl+Di	NF/S-L, 120V, 6A, 50W, 50MHz, B>2000	18c	Sak	(2SD1170, 2SD1210)
2SD2046	Si-N-Darl+Di	int. Z-Di, 50V, 1,5A, 1W, B=2k..10k	7c(H)	Hit	2SD1809, 2SD1666, 2SD1929, 2SD1931, ++
2SD2047(R)	Si-N	S-L, TV-HA, 1500V, 5A, 60W	18c	Fjd	BU2506AF, 2SC3894, 2SD1545, 2SD1655, ++
2SD2048	Si-N-Darl+Di	NF/S-L, 110V, 3A, 30W, 20MHz, B=4000	30c(A)	Say	—
2SD2049	Si-N-Darl+Di	NF/S-L, 110V, 5A, 35W, 20MHz, B=4000	30c(A)	Say	—
2SD205	Si-N	NF/S-L, 60V, 0,7A, 9W(Tc=25°)	2a	Nec	(BD137, BD226, BD517, BD525, ++)
2SD2050	Si-N-Darl+Di	NF/S-L, 110V, 6A, 40W, 20MHz, B=4000	30c(A)	Say	—
2SD2051	Si-N-Darl+Di	int Z-Di, 60V, 1,6A, 12W, >200MHz, B>4k	17c	Mat	2SD1983
2SD2052	Si-N	NF/S-L, 150/150V, 9A, 100W, 20MHz	18c	Mat	(BD245D, 2SC2837, 2SC3907, 2SD1046, ++)
2SD2053	Si-N	=2SD2052:	18j	Mat	BD245D, 2SC2837, 2SC3907, 2SD1046, ++
2SD2054	Si-N	SMD, NF, 100V, 1A	39b	Hit	BCX56, 2SD1005, 2SD1368, 2SD1416..19, ++
2SD2055	Si-N	NF/S-L, 60V, 10A, 40W	17j	Rhm	BD709, BD743B, BD609, BD909, ++
2SD2056	Si-N	=2SD2055: Iso, 30W	17c	Rhm	2SC3693..3894
2SD2057	Si-N+Di	S-L, TV-HA, 1500/700V, 5A, 100W	18c	Mat	BU508DF, 2SC4122, 2SC4293, 2SD1555, ++
2SD2056	Si-N	NF/S-L, 60V, 3A, 25W, 3MHz, <0,8/2,3µs	17c	Kec	2SC3851..52, 2SD1585, 2SD1965, 2SD2012++
2SD2059	Si-N	NF/S-L, 100V, 5A, 30W, 12MHz	17c	Kec	2SC3691, 2SD1566, 2SD1940
2SD206(A)	Si-N	NF/S-L, 50V, 10A, 150W	23a	Shi	BD315, 2N5829. 31, 2SC2606, 2SD1105, ++
2SD2060	Si-N	NF/S-L, 60V, 4A, 25W, 8MHz	17c	Kec	2SC3691, 2SC3851, 2SD2000
2SD2061	Si-N	=2SD2023: Iso	17c	Rhm	2SC3691, 2SC3851, 2SD2000
2SD2062	Si-N	NF/S-L, 100/60V, 7A, 60W, 8MHz	16c(j)	Rhm	(BD245C, BD545C, 2SC2681, 2SD1840, ++)
2SD2063	Si-N	NF, hi-beta, 15V, 1A, 0,9W, B=700	7c(9mm)	Hit	2SC3070, 2SC3225, 2SC3726, 2SD1984
2SD2064	Si-N	NF/S-L, 120/120V, 6A, 70W, 20MHz	16c	Mat	(BD245D, BD545D, 2SC2706, 2SC2837, ++)
2SD2065	Si-N	NF/S-L, 140/140V, 7A, 60W, 20MHz	18c	Mat	(BD245D, 2SC2706, 2SC2637, 2SC3907, ++)
2SD2066	Si-N	NF/S-L, 160/160V, 12A, 120W, 20MHz	18j	Mat	BD745F, 2SC2987A, 2SC3907, 2SD1047, ++
2SD2067	Si-N-Darl+Di	Uni, 120/100V, 2A, 1W, B>4k	9c	Mat	2SD1579, 2SD1659, 2SD1978
2SD2068	Si-N-Darl+Di	Uni, int. Z-Di, 60V, 1A, 1W, B>4k	7c(9mm)	Mat	2SD1609, 2SD1866, 2SD1929, 2SD1931, ++
2SD2069	Si-N	lo-sat, 60V, 2A, 1W, 210MHz	7c(9mm)	Rhm	2SC3326, 2SC4468, 2SD1207, 2SD2177

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2SD207(A)	Si-N	=2SD206: 100V	23a	Shi	BD317, 2N5629..31, 2SC2608, 2SD1105, ++
2SD2070	Si-N	Uni, 50V, 0,1A, 1W	9c	Mat	BC174, BC182, BC190, BC546, ++
2SD2071	Si-N	Uni, 50V, 0,5A, 1W, 200MHz	9c	Mat	BC337..338, BC635, BC637, BC639, ++
2SD2072	Si-N	=2SD661: 1W, Pins=14mm	9c	Mat	→2SD661
2SD2073	Si-N	=2SD1010: 1W	9c	Mat	→2SD1010
2SD2074	Si-N	=2SD1302: 1W	9c	Mat	→2SD1302
2SD2075	Si-N+Di	hi-beta, lo-sat, 60V, 10A, 90MHz, B>500	17c	Tos	2SD1947
2SD2076	Si-N+Di	hi-beta, lo-sat, 100V, 5A, 90MHz, B>500	17c	Tos	2SD1947
2SD2079	Si-N-Darl+Di	NF/S-L, 100V, 5A, 30W, B=2k..15k	17c(A)	Tos	BD647F, 2SD1589, 2SD1829..30, 2SD1785++
2SD208(A)	Si-N	=2SD206: 150V	23a	Shi	BDW12, MJ15015, 2N3773, 2SC2607..08, ++
2SD2081	Si-N-Darl+Di	NF/S-L, 120/120V, 10A, 30W, B>2000	17c(A)	Sak	BDT63CF, BDT65CF, 2SD1591
2SD2082	Si-N-Darl+Di	NF/S-L, 120/120V, 16A, 75W, B>2000	18c	Sak	—
2SD2083	Si-N-Darl+Di	NF/S-L, 120/120V, 25A, 120W, B>2000	16c(A)	Sak	2SD1597
2SD2084	Si-N-Darl	S-L, 450/450V, 8A, 50W, B>1000	17j		BU810, BU911..912, 2SD798..799, ++
2SD2085	Si-N	hi-beta, 60V, 6A, 40W, 50MHz, B>400	17j	Rhm	(2SC2315..16,. 2SC2491)
2SD2088	Si-N-Darl+Di	+Z-Di, 60V, 2A, 0,9W, 100MHz, B>2000	7c	Tos	2SD1153, 2SD1809, 2SD1854, 2SD1929, ++
2SD2089	Si-N+Di	CTV-HA, 1500/600V, 3,5A, 40W	18c	Tos	BU2508DF, 2SD1554, 2SD1850, 2SD1877, ++
2SD2090	Si-N-Darl+Di	int. Z-Di(B→C), 90V, 2A, 25W, B>1000	17j	Rhm	—
2SD2091	Si-N-Darl+Di	=2SD2090: Iso	17c	Rhm	—
2SD2092	Si-N+Di	hi-beta, lo-sat, 100V, 3A, 140MHz, B>500	17c	Tos	2SD2078
2SD2093	Si-N-Darl+Di	110V, 10A, 45W, 20MHz, B=4000	≈18c	Say	(BDV65C, BDV67BD), BDW83D)
2SD2094	Si-N-Darl+Di	NF-L, 120/120V, 8A, 25W, B>1000	17c(A)	Hit	BD649F, 2SD1773
2SD2095	Si-N+Di	CTV-HA, 1500/600V, 5A, 50W	18c	Tos	BU508DF, 2SD1555, 2SD1851, 2SD2125
2SD2096	Si-N	=2SD2023: 1,8W	76c	Rhm	(BD441, BD787, BD789, MJE240..241)
2SD2097	Si-N	=2SD1981: Pins=14mm	9c	Rhm	2SC3671, 2SC4482, 2SD1145
2SD2098	Si-N	=2SD1981: SMD	39b	Rhm	2SD1828
2SD2099	Si-N+Di+R	Motor-Tr, lo-sat, 40V, 3A Rb=90Ω, Rbe=600Ω	39b	Say	2SD1624
2SD21	Ge-N	=2SD19: B=72	2a	Nec	AC127, AC176, AC187, 2SD72, 2SD352
2SD2100	Si-N+Di+R	SMD, lo-sat, 25V, 2A, Rb=0, Rbe=1,6kΩ	39b	Say	2SD1621
2SD2101	Si-N-Darl	NF-L, 200/200V, 10A, 30W, B>1500	17c	Hit	2SD1794
2SD2102	Si-N-Darl	NF-L, 60V, 4A, 25W, B>1000	17c	Hit	BDT61(AB,C)F, 2SD1595, 2SD2131, ++
2SD2103	Si-N-Darl	NF-L, 60V, 8A, 25W, B>1000	17c	Hit	BD643F, 2SD1415..17, 2SD1826..27, ++
2SD2104	Si-N-Darl+Di	NF-L, 120/120V, 8A, 25W, B>1000	17c	Hit	BD649F, BD651F, 2SD1590
2SD2105	Si-N-Darl+Di	NF-L, 120/120V, 10A, 30W, B>1000	17c	Hit	BDT63CF, 2SD1591
2SD2106	Si-N-Darl+Di	NF-L, 120/120V, 6A, 25W, B>1000	17c	Hit	BD649F, BD651F, 2SD1336, 2SD1590
2SD2107	Si-N	NF-L, 70V, 4A, 25W	17c	Hit	BD951F, BD953F, BD955F, 2SD1407
2SD2108	Si-N-Darl+Di	NF-L, 60V, 6A, 25W, B>1000	17c	Hit	BD645F, BD647F, 2SC4062, 2SD1415..18++
2SD2109	Si-N-Darl	S-L, 300/300V, 0,3A 15W, B>1000	17c	Hit	(2SD1502, 2SD1798)
2SD211	Si-N	NF/S-L, 60V, 10A, 100W, -/4,4µs	23a	Sak	BD311, BDW21A2N3055, 2N5877..78, ++
2SD2110	Si-N-Darl+Di	NF-L, 60V, 4A, 25W, B>1000	17c	Hit	BDT61(A..C)F, 2SD1933, 2SD2014, ++
2SD2111	Si-N-Darl+Di	NF-L, 120/120V, 3A, 25W, B>1000	17c	Hit	BDT61CF, 2SD2014..15
2SD2112	Si-N-Darl+Di	NF-L, 120/120V, 8A, 25W, B>1000	17c	Hit	BD649F, BD651F, 2SD1336
2SD2113	Si-N-Darl+Di	NF-L, 120/120V, 3A, 25W, B>1000	17c	Hit	BDT61CF, 2SD2014..15
2SD2114K	Si-N	=2SD2132: SMD	35a	Rhm	—
2SD2115L,S	Si-N	NF-L, 150/60V, 2A, 18W	30j	Hit	2SD1033, 2SD1557
2SD2116	Si-N-Darl	Uni, 50V, 0,7A, 1W, 200MHz, B>5000	9c(C)	Say	BC618, BC877, BC879, 2SD1153, ++
2SD2117	Si-N-Darl	Uni, 50V, 1,5A, 1W, B>4000	9c(C)	Say	2SD1153, 2SD1660, 2SD1853..54, 2SD1981, +
2SD2118(F5)	Si-N	NF, 50V, 5A, 1W, 150MHz	30c	Rhm	2SC3072, 2SC3074, 2SD1803, 2SD1605, ++
2SD2119	Si-N-Darl	NF-L, 90V, 4A, 25W, B>2000	17c	Rhm	BDT81BF..CF, 2SD1414, 2SD1788, 2SD2079+
2SD212	Si-N	=2SD211: 90V	23a	Sak	BD313, BDW21C, 2N3055, 2N5632..33, ++
2SD2120	Si-N-Darl+Di	Uni, 100V, 2A, 1W, B=2k..30k	9c	Say	2SD1660, 2SD1981
2SD2121L,S	Si-N	NF-L, 35V, 2,5A, 18W	30j	Hit	2SC3386, 2SD1221, 2SD1802
2SD2122L,S	Si-N	NF-L, 180/120V, 1,5A, 18W, 180MHz	30j	Hit	2SC4027, 2SC108082
2SD2123L,S	Si-N	NF-L, 180/160V, 1,5A, 18W, 180MHz	30j	Hit	2SC4027
2SD2124L,S	Si-N-Darl+Di	NF-L, 120/120V, 1,5A, 18W, B>2000	30j	Hit	2SD1484..65
2SD2125	Si-N+Di	CTV-HA, 1500/600V, 6A, 50W	18c	Tos	BU508DF, 2SC3892A, 2SD1556, 2SD1652
2SD2127	Si-N+Di	hi-beta, lo-sat, 60V, 3A, 140MHz, B>500	17c	Tos	2SD1948, 2SD1972, 2SD2076
2SD2128	Si-N-Darl+Di	NF-L, 60V, 3A, 25W, B>1000	17c	Hit	BDT61(A..C)F, 2SD1413, 2SD1798, ++
2SD2129	Si-N-Darl+Di	S-L, 100V, 3A, 20W, B=2000..15000	17c	Tos	2SD1414, 2SD1788, 2SD1828, 2SD2015
2SD213	Si-N	=2SD211: 110V	23a	Sak	BDW21C, 2N3055, 2N5632..33, 2SD551, ++
2SD2130	Si-N-Darl+Di	+Z-Di, 60V, ±4A, 10W, 60MHz, B=2k..15k	14b	Tos	2SD1798
2SD2131	Si-N-Darl+Di	+Z-Di, 60V, 5A, 30W, B=2000..15000	17c(H)	Tos	2SD1595
2SD2132	Si-N	lo-sat, hi-beta, 25V, Ueb=12V, 0,5A, B>560	7c	Rhm	2SC4204, 2SD2144..45, 2SD2191..92
2SD2133	Si-N	NF-E, 60V, 1A, 1,5W, 200MHz	78b	Mat	(BD135, BD137, BD139, BD226, ++)
2SD2134	Si-N	NF-E, 180/160V, 1A, 1,5W, 200MHz	78b	Mat	(2SC3117, 2SC3902, 2SD669)
2SD2135	Si-N-Darl+Di	int. Z-Diode, 60V, 1A, 150MHz, B>6500	78b	Mat	—

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2SD2136	Si-N	NF-E/S, 60V, 3A, 1,5W, 500/2900ns	78b	Mat	(BD177, BD179, BD189, 2SD794(A))
2SD2137	Si-N	NF-E/S, 60V, 3A, 15W, 30MHz	78c	Mat	(BD177, BD179, BD189, 2SD794(A))
2SD2137A	Si-N	=2SD2137: 60V	78c		(BD179, BD189, 2SD794(A))
2SD2136	Si-N-Darl+Di	NF-E, 60V, 2A, 15W, 20MHz, B>1000	78c	Mat	BDT61(A..C)F, 2SD1413, 2SD1983, ++
2SD2136A	Si-N-Darl+Di	=2SD236: 80V	78c		BDT61(A..C)F, 2SD1414, 2SD1933
2SD2139	Si-N	hi-beta, 60V, 3A, 15W, 50MHz, B>500	78c	Mat	2SD1776, 2SD2092, (2SC1983, 2SD1774)
2SD214	Si-N	=2SD211: 130V	23a	Sak	BDX11, 2N3442, 2SD551, 2SD732..733, ++
2SD2140	Si-N	NF-E, 140/140V, 7A, 80W, 20MHz	18j	Mat	BD245D, 2SC2706, 2SC2837, 2SC3182, ++
2SD2141	Si-N-Darl+Di	S-L, +Z-Di, 380V, 6A, 35W, B>1500	17c	Sak	—
2SD2143	Si-N-Darl	int. Z-D(B→C), 60±10V, 2A, 10W, B>1k	79c(H)	Rhm	—
2SD2144(S)	Si-N	=2SD2132: 0,3W	41c	Rhm	→2SD2132
2SD2145(M)	Si-N	=2SD2132: 0,4W	9c	Rhm	→2SD2132
2SD2146	Si-N	NF, 60V, 3A, 1,2W, 90MHz	78b	Rhm	2SC3386, 2SC4522, 2SD1802, 2SD1221, ++
2SD2147	Si-N	Blitzg./Strobo Fl., NF, 50V, 5A, 150MHz	14h	Rhm	2SC2270, 2SD826
2SD2148	Si-N	S-L, HA, 1500/700V, 8A, 50W	≈13c	Hit	BU508AF, 2SC3886A, 2SC3896
2SD2149	Si-N-Darl+Di	S-L, 100/100V, 15A, 100W, B>1000	13j	Hit	BDV67A..D, BDW83C..D, 2SD1026
2SD215	Si-N	NF/S, 40V, 1A, 0,8W	2a	Fui	BC140..141, 2N1990, 2N2102, 2N2405, ++
2SD2150	Si-N	=2SD2152: SMD	39b	Rhm	2SD1119, 2SD1624
2SD2151	Si-N	NF-L, 130/80V, 10A, 30W, 20MHz	17c	Mat	2SC3568, 2SC3698, 2SC4338
2SD2152	Si-N	NF-Tr, 40V, 3A, 0,75W, 290MHz	7c	Rhm	2SC4487, 2SD1507, 2SD1617, 2SD1864, ++
2SD2153	Si-N	hi-beta, 30/25V, 2/3A, B=390..2700	39b	Rhm	2SC3439, 2SC3727
2SD2154	Si-N	=2SD2152: 0,8W	9c	Rhm	→2SD2152
2SD2155	Si-N	HiFi-NF-E, 180V, 15A, 150W, 10MHz	77j	Tos	2SC3281, 2SC4029
2SD2156	Si-N	hi-beta, 60V, 3A, 25W, 50MHz, B>500	17c	Mat	2SD1944, 2SD2078, 2SD2092
2SD2156A	Si-N	=2SD2156: 100V	17c		2SD2076, 2SD2092
2SD2157	Si-N-Darl+Di	NF-L, 60V, 4A, 25W, 20MHz, B>1000	17c(A)	Mat	BDT61(A..C)F, 2SD1825, 2SD1967, 2SD2014
2SD2157A	Si-N-Darl+Di	=2SD2157: 80V	17c(A)		BDT61(A..C)F, 2SD1414, 2SD1788, 2SD1933
2SD2158	Si-N	hi-beta, 60V, 2A, 20W, 40MHz, B>500	17c	Mat	2SC3852, 2SD1778(A), 2SD1944, 2SD2092
2SD2158A	Si-N	=2SD2158: 100V	17c		2SD1776A, 2SD2092, 2SD2156A
2SD2159	Si-N	hi-beta, lo-sat, 30V, 2A, 1W, 110MHz	7c(9mm)	Rhm	2SC3225, 2SC4389,
2SD216	Si-N	=2SD215: 80V	2a	Fui	BC140..141, 2N1990, 2N2102, 2N2405, ++
2SD2161	Si-N-Darl+Di	=2SD1589	17c	Nec	→2SD1589
2SD2162	Si-N-Darl+Di	=2SD1590	17c	Nec	→2SD1590
2SD2163	Si-N-Darl+Di	=2SD1591	17c	Nec	→2SD1591
2SD2164	Si-N	=2SD2152: 1W	9c	Rhm	→2SD2152
2SD2164	Si-N	=2SD1593	17c	Nec	→2SD1593
2SD2165	Si-N	=2SD1594	17c	Nec	→2SD1594
2SD2166	Si-N	=2SD2147: Iso	14b	Rhm	2SC3420, 2SD1685
2SD2167	Si-N	=2SD2169: SMD	39b	Rhm	—
2SD2168	Si-N	=2SD2169	9c	Rhm	—
2SD2169	Si-N	int. Z-Di(C→B), 31V, 2A, 0,5W, 100MHz	9c	Rhm	—
2SD217	Si-N	NF/S-L, 120V, 7A, 60W, 10MHz	23a	Nec	BD245D, 2N3442, 2SD551, 2SD731..732, ++
2SD2170	Si-N-Darl+Di	SMD, int Z-Dioda, 90V, 2A, 60MHz, B>1000	39b(H)	Rhm	—
2SD2171S	Si-N	hi-beta, hi-Ueb, 30V, 1,5A, 0,3W, 200MHz	41c	Rhm	2SC3070, 2SD1582
2SD2172	Si-N	=2SD2171S: 1W	7c(9mm)	Rhm	2SC4389
2SD2175	Si-N	Uni, -/80V, 0,7A, 0,5W	9c	Rhm	BC639, 2SD774, 2SC3665, 2SD1226, ++
2SD2176	Si-N-Darl+Di	Motor-Tr, 50V, 1,2A, B>1000, Z-Di(B→C)	39b	Say	2SD1628
2SD2177	Si-N	NF-E, lo-sat, 50V, 2A, 1W, 110MHz	9c	Mat	2SC3328, 2SD1207, 2SD1835, 2SD2182
2SD2178	Si-N	=2SD2177: 1,5W	78b	Mat	—
2SD2179	Si-N	Uni, 50V, 5A, 1W, 80MHz	9c	Mat	2SD1145, 2SD1961..82, 2SD2097
2SD218	Si-N	=2SD217: 150V	23a	Nec	BD245D, 2N3442, 2SD551, 2SD731..732, ++
2SD2180	Si-N	Uni, 50V, 3A, 1,5W, 80MHz	78b	Mat	—
2SD2181	Si-N	Uni, lo-sat, 100V, 1A, 1W, 100MHz	9c	Mat	2SC4488, (BC639, 2SD1818A, 2SD1786)
2SD2182	Si-N	Uni, lo-sat, 100V, 2A, 1W, 60MHz	9c	Mat	2SC4489, (2SD1015, 2SD1642)
2SD2183	Si-N	=2SD2182: 1,5W	78b	Mat	—
2SD2184	Si-N	NF, lo-sat, 150/150V, 1A, 1W, 90MHz	9c	Mat	(2SD1812)
2SD2185	Si-N	=2SD2177: SMD, 3A	39b	Mat	2SC4409, 2SD1823
2SD2189	Si-N	=2SD2085: Iso, 30W	17c	Rhm	2SC4553, (2SC4568, 2SD1474)
2SD219	Si-N	NF/S, 40V, 1A, 0,5W, 340/5000ns	2a	Sak	BC140..141, 2N1990, 2N2102, 2N2405, ++
2SD2191	Si-N	=2SD2132: 0,4W, Pins=14mm	9c	Rhm	→2SD2132
2SD2192	Si-N	=2SD2132: 0,4W, Pins=14mm	9c	Rhm	→2SD2132
2SD2193	Si-N+Di	Z-Di, hi-beta, 25V, 0,6A, 0,9W, B>800	7c(9mm)	Hit	—
2SD2195	Si-N-Darl+Di	SMD, Uni, 100/100V, 2A, B=1k..10k	39b(A)	Rhm	2SD1472
2SD2196	Si-N-Darl+Di	=2SD1027: Iso, 55W	82c(E)	Shi	(2SD1515)
2SD2197M	Si-N	=2SC2069:	9c	Rhm	→2SC2069
2SD2198	Si-N	S-L, lo-sat, 80V, 5A, 30W, 100/1800ns	30c	Say	2SD1904, 2SD1906, 2SD2200

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2SD2199	Si-N	S-L, Io-sat, 60V, 7A, 40W, 200/1200ns	30c	Say	2SD1905, 2SD1907, 2SD2201
2SD219F	Si-N	=2SD222:	43a		→2SD222
2SD22	Ge-N	=2SD19: B=97	2a	Nec	AC127, AC176, AC187, 2SD72, 2SD352
2SD220	Si-N	=2SD219: 30V	2a	Sak	BC140..141, 2N1990, 2N2102, 2N2405, ++
2SD2200	Si-N	S-L, Io-sat, 90V, 5A, 30W, 100/1600ns	30c	Say	2SD1906..07, 2SD2201
2SD2201	Si-N	S-L, Io-sat, 90V, 7A, 40W, 100/2000ns	30c	Say	2SD1907
2SD2202	Si-N	S-L, Io-sat, 90V, 5A, 25W, 20MHz	17c	Say	2SD1411
2SD2203	Si-N	S-L, Io-sat, 90V, 7A, 30W, 20MHz	17c	Say	2SD1411
2SD2204	Si-N-Darl+Di	int Z-Di, 65V, 4A, 25W, B=2k..15k	17c	Tos	—
2SD2205	Si-N-Darl+Di	=2SD1590	17c	Nec	→2SD1590
2SD2206	Si-N-Darl+Di	Uni, 100V, 2A, 0,9W, 100MHz, B>2000	7c(A)	Tos	2SD1978, 2SD1981
2SD2209	Si-N-Darl+Di	int Z-Diode, 100/100V, 4A, 15W, B>1000	30j	Mat	2SC4345, 2SD1223, 2SD1520
2SD220F	Si-N	=2SD223:	43a		→2SD223
2SD221	Si-N	=2SD219: 110V	2a	Sak	BC141, 2N1990, 2N2102, 2N2405, ++
2SD2210	Si-N	=2SD1302: SMD	39b	Mat	2SC2982, 2SC3265, 2SD1821
2SD2211	Si-N	=2SD1918: SMD	39b	Rhm	2SC3649, 2SD1420..21
2SD2212	Si-N-Darl+Di	SMD, Z-Di(B→C), 60V, 2/3A, 80MHz, B>1k	39b	Rhm	—
2SD2213	Si-N-Darl+Di	NF, 150/60V, 1,5A, 0,9W, B>5000	7c	Hit	2SD1579, 2SD1659
2SD2214	Si-N-Darl	S-L, 60V, 8A, 25W, 20MHz, B>2000	17c	Mat	—
2SD2215(A)	Si-N	=2SD1249(A): 15W	≈30j	Mat	2SC3075
2SD2216	Si-N	SMD, C7394Uni, 60V, 0,1A, 150MHz	35a(1,6mm)	Mat	2SC4736
2SD2217	Si-N-Darl	S-L, 300/300V, 0,3A, 25W, 45MHz, B>1500	17c	Nec	2SD2109
2SD2218	Si-P	S-L, 60V, 8A, 20W, 120MHz, 100/530ns	17c	Say	BD201F, BD203F, 2SD1412, 2SD1668, ++
2SD2219	Si-P	S-L, 60V, 12A, 25W, 120MHz, 200/530ns	17c	Say	2SC3709, 2SC4065
2SD221F	Si-N	=2SD224:	43a		→2SD224
2SD222	Si-N	=2SD219: 1,5A, 10W	43a	Sak	(BD135, BD226, BD233, BD507, ++)
2SD2220	Si-N-Darl	NF-E, 100/60V, 1A, 1,5W, 150MHz, B>4000	78b	Mat	—
2SD2221	Si-N-Darl	L, 160/140V, 7A, 100W, 20MHz, B>5000	18j	Mat	2SD2255
2SD2222	Si-N-Darl	L, 160/160V, 8A, 150W, 20MHz, B>3500	77j	Mat	2SD2250, 2SD2276
2SD2223	Si-N-Darl	L, 70V, 4A, 30W, 600/4300ns, B>2000	30c(A)	Say	(BDW23BC, BDW63B..D, 2SD1933, ++)
2SD2224	Si-N-Darl	L, 70V, 7A, 35W, 600/4700ns, B>2000	30c(A)	Say	(BD847, BD899, BDW73B, 2SD1415..16++)
2SD2225	Si-N	=2SD1211:	9c	Mat	2SC2235, 2SC3665, 2SD667, 2SD1616A
2SD2226K	Si-N	=2SD2227S: SMD	35a	Rhm	2SD1936
2SD2227S	Si-N	hi-beta, hi-Ueb, 60V, 0,15A, 250MHz	41c	Rhm	2SC3069, 2SC3071, 2SC3836
2SD2228	Si-N	SMD, Uni, Io-sat, 25V, 0,5A, 50MHz	35a(2mm)	Nec	—
2SD2229	Si-N	Uni, Io-sat, 16V, 0,5A, 0,25W, >50MHz	40c	Nec	2SC3225, 2SC3247, 2SC4483, 2SD1302, ++
2SD223	Si-N	=2SD219: 60V, 1,5A, 10W	43a	Sak	(BD139, BD230, BD237, BD527, ++)
2SD2230	Si-N	=2SD2229: SMD	35a	Nec	2SC3265, 2SC4519
2SD2231	Si-N-Darl+Di	NF-L, 120/120V, 8A, 60W, B>2000	16c(A)	Sak	2SD1170
2SD2232	Si-N-Darl	S-L, 400/300V, 8A, 30W, 20MHz, B>3000	17c	Mat	(2SD1141)
2SD2233	Si-N-Darl	S-L, 300/250V, 8A, 30W, 20MHz, B>2700	17c	Mat	2SD1410, 2SD2017
2SD2234	Si-N	S-L, 1500V, 3A, 40W, <1/4,5µs	17c	Fjd	BU505F, 2SD1575
2SD2236	Si-N	L, -/100V, 5A, 60W	16c	Rhm	2SC4365, 2SC4689, 2SC5099, (BD245D, ++)
2SD2237	Si-N-Darl+Di	L, -/100V, 8A, 60W, B>2000	16c	Rhm	BDV65CF, 2SD1670, 2SD1895
2SD224	Si-N	=2SD219: 110V, 1,5A, 10W	43a	Sak	(BD139, BD230, BD237, BD529, ++)
2SD2240(A)	Si-N	=2SD814(A):	36a(1,6mm)	Mat	—
2SD2241	Si-N-Darl+Di	L, 100V, ±4A, 25W, B>2000, 200/2100ns	17c(A)	Tos	—
2SD2242	Si-N-Darl+Di	NF/S-L, 60V, 4A, 15W, 20MHz, B>1000	76c	Mat	(BDT61(A..C)F, 2SD1325, 2SD2014, ++)
2SD2242A	Si-N-Darl+Di	=2SD2242: 60V	76c		(BDT61AF..CF, 2SD1933, 2SD2014, ++)
2SD2243	Si-N	Io-sat, 60/60V, 5A, 1W	9b	Nec	2SC4482, 2SD1145
2SD2244	Si-N	hi-beta, Io-sat, 60/60V, 3A, 1W, B>600	9b	Nec	—
2SD2245	Si-N-Darl+Di	int. Z-Di(B→C), 60V, ±2A, 1W, B>2000	9b	Nec	—
2SD2246	Si-N-Darl+Di	60/80V, ±2A, 1W, B>2000, 0,4/1,9µs	9b	Nec	2SD1153, 2SD1809, 2SD1653, 2SD1866
2SD2247	Si-N	Uni, 55V, 0,1A, 0,2W, 50MHz	7c	Hit	BC167, BC237, BC546..547, 2SD787, ++
2SD2246	Si-N-Darl+Di	+Z-Di, 60V, ±2A, 0,9W, 100MHz, B>2000	7c	Tos	2SD1981
2SD2249	Si-N	=2SD965: 1W	9c	Mat	2SD1244, 2SD1934, 2SD1981..62, 2SD2097++
2SD2250	Si-N-Darl	S-L, 160/140V, 7A, 90W, 20MHz, B>5000	77j	Mat	2SD2222, 2SD2276
2SD2251	Si-N+Di	=2SC4770: int. Damper-Diode	16c	Say	BU508DF, 2SC3893A, 2SC4123..24, 2SC4769
2SD2252	Si-N	CTV-HA, 1500/600, 7A, 60W	16c	Say	BU508AF, 2SC3685A, 2SC3895, 2SC4770
2SD2253	Si-N+Di	CRT HA, VGA, 1700/600, 8A, 50W	16c	Tos	2SC4766
2SD2254	Si-N-Darl	L, 130/110V, 8A, 70W, 20MHz, B>5000	77j	Mat	2SD2222, 2SD2250, 2SD2276
2SD2255	Si-N-Darl	L, 160/140V, 7A, 70W, 20MHz, B>5000	18j	Mat	2SD2221
2SD2256	Si-N-Darl+Di	S-L, 120/120V, 25A, 120W, B>2000	18j	Hit	2SD2083
2SD2257	Si-N-Darl+Di	S-L, 100V, ±3A, 20W, 500/2500ns, B>2k	17c(A)	Tos	BDT61BF, 2SD1828, 2SD2129, 2SD1788, ++
2SD2256	Si-N-Darl	=2SD1198A: 1W, Pins=14mm	9c	Mat	→2SD1198A
2SD2259	Si-N	=2SD1458: 1W, Pins=14mm	9c	Mat	→2SD1458

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2SD226	Si-N	NF/S-L, 40V, 3A, 25W	22a	Mat	BD241, BD243, BD533, BD933,++
2SD2260	Si-N	=2SD662B: 0,6W, Pins=14mm	9c	Mat	→2SD662B
2SD2261	Si-N-Darl	SMD, 80/60V, 2,5A, B>2000	39b(A)	Say	—
2SD2263	Si-N+Di	int. Z-Di(C→B), 25V, 0,5A, 0,5W	7c	Hit	—
2SD2264	Si-N	=2SD2152:	9c	Rhm	→2SD2152
2SD2265	Si-N-Darl	S-L, 1000V, 1A, 35W, 20MHz, B>200	30j	Mat	—
2SD2266	Si-N	S-L, 60V, 4A, 15W, 80MHz	73j	Mat	(BD243B..F, BD539B..D, 2SC3254)
2SD226A	Si-N	=2SD226: 60V	22a		BD241A, BD243A, BD535, BD935
2SD226B	Si-N	=2SD226: 60V	22a		BD241B, BD243B, BD537, BD937
2SD227	Si-N	Uni, 30V, 0,3A, 0,25W, 120MHz	7c	Nec, Mic	BC337..338, BC635, BC637, BC639, ++
2SD2271	Si-N-Darl	300/200V, 10A, 30W, B>500, <1/14µs	15c(A)	Tos	—
2SD2273	Si-N-Darl	L, 100/80V, 3A, 45W, 20MHz, B>5000	77j	Mat	2SD2254
2SD2274	Si-N-Darl	L, 110/90V, 4A, 50W, 20MHz, B>5000	77j	Mat	2SD2254
2SD2275	Si-N-Darl	L, 120/100V, 5A, 60W, 20MHz, B>5000	77j	Mat	2SD2254
2SD2276	Si-N-Darl	L, 160/140V, 8A, 120W, 20MHz, B>5000	77j	Mat	2SD2222, 2SD2250
2SD2279	Si-N	=2SD2069:	9c	Rhm	→2SD2069
2SD228	Si-N	=2SD227: 0,4W	7c*	Nec	BC337..338, BC635, BC637, BC639, ++
2SD2260	Si-N	S-L, 60V, 7A, 40W, 10MHz, 200/1200ns	19c	Say	2SC4385, 2SD2064, (BD245A..F,++)
2SD2281	Si-N	S-L, 60V, 12A, 45W, >30MHz, 100/1250ns	18c	Say	(BD545A..D, 2SC3256, 2SD1064..65,++)
2SD2282	Si-N	S-L, 60V, 15A, 50W, 20MHz, 200/1100ns	18c	Say	(BD545A..D, 2SC3256, 2SD1064..65,++)
2SD2283	Si-N-Darl+Di	=2SD2090: 1,8W	17c(A)	Rhm	—
2SD2284	Si-N-Darl	80V, 3A, B>2000	12b(A)	Say	—
2SD2285	Si-N	S-L, 60V, 20A, 40W, 300/620ns	18c	Say	—
2SD2287	Si-N+Di	CTV-HA, 1500V, 3A, 50W	23a	Hit	BU206D, BU706D, 2SC3460, 2SD1877, ++
2SD2266	Si-N	CTV-HA, 1500/800V, 3A, 50W	23a	Hit	BU206A, BU705, 2SC3023, 2SD850, ++
2SD2289	Si-N+Di	CTV-HA, 1500V, 5A, 50W	23a	Hit	BU206D, BU708D, 2SC3481, 2SD1878,++
2SD2290	Si-N	CTV-HA, 1500/800V, 5A, 50W	23a	Hit	BU208A, BU706, 2SC2928, 2SC3685, ++
2SD2291	Si-N+Di	CTV-HA, 1500V, 8A, 50W	23a	Hit	BU508D, 2SC3682, 2SD1732, 2SD1879, ++
2SD2292	Si-N	CTV-HA, 1500/800V, 8A, 50W	23a	Hit	BU508A, 2SC3025, 2SC3686, 2SD725, ++
2SD2293	Si-N+Di	=2SD2287:	18j	Hit	BU506D, BU706D, 2SD1729, 2SD1877,++
2SD2294	Si-N	=2SD2266:	18j	Hit	BU705, 2SC3464, 2SD1495
2SD2295	Si-N+Di	=2SD2289:	18j	Hit	BU508D, BU708D, 2SC3481, 2SD1878,++
2SD2296	Si-N	=2SD2290:	18j	Hit	BU508A, BU706, 2SC3685, 2SD1496..97,++
2SD2297	Si-N+Di	=2SD2291:	18j	Hit	BU508D, 2SC3682, 2SD1732, 2SD1879, ++
2SD2298	Si-N	=2SD2292:	18j	Hit	BU506A, BU908, 2SC3666, 2SD1497,++
2SD2299	Si-N+Di	=2SD2287: Iso	≈18c	Hit	BU705DF, 2SD1553..54, 2SD1649..50,++
2SD23	Ge-N	=2SD19: B=150	2a	Nec	AC127, AC176, AC187, 2SD72, 2SD352
2SD2300	Si-N+Di	=2SD2289: Iso	≈18c	Hit	BU706DF, 2SD1555..58, 2SD1651..52,++
2SD2301	Si-N	=2SD2292: Iso	≈18c	Hit	BU506DF, 2SC3685A, 2SC3895, 2SC4770, ++
2SD2306	Si-N-Darl+Di	L, -/60V, 4A, B>1000	17c(A)	Rhm	2SD1233, 2SD1520
2SD2307	Si-N-Darl+Di	L, -/100V, 8A, B>1000	17c(A)	Rhm	—
2SD2308	Si-N-Darl+Di	NF, 60V, 4A, 1,2W, 40MHz, B=5000	14b(A)	Rhm	2SD1223, 2SD1520
2SD2309	Si-N-Darl	=2SD1986:	14b(A)	Rhm	2SD1223, 2SD1520
2SD231	Si-N	NF/S-L, 60V, 30A, 125W, -/11µs	23a	Fui	BDX41, 2N3771, 2SD830
2SD2310	Si-N+Di	S-L, TV-HA, 1500/700, 1,5A, 40W	17c	Mat	BU505DF, 2SD2001
2SD2311	Si-N	=2SD2290: Iso	≈18c	Hit	BU506AF, BU706F, 2SC3894, 2SD1655..56+
2SD2312	Si-N	=2SD2227S: 0,4W	9c	Rhm	→2SD2227S
2SD2313M	Si-N	=2SD2227S: 0,4W	9c	Rhm	→2SD2227S
2SD2314	Si-N	=2SD2227S: 0,4W, Pins=14mm	9c	Rhm	→2SD2227S
2SD2315	Si-N	=2SD2227S: 0,4W, Pins=14mm	9c	Rhm	→2SD2227S
2SD2318(F5)	Si-N	hi-beta, 80/60V, 3A, 15W, 50MHz, B>390	30j	Rhm	2SD1754
2SD232	Si-N	=2SD231: 120V, -/13,5µs	23a	Fui	BDW30, 2N6032, 2N6274..8275
2SD2321	Si-N	NF-E, 40V, 5A, 0,4W, 150MHz	41c	Mat	2SD1244, 2SD1934, 2SD2249, 2SD2097, ++
2SD2322S	Si-N	lo-sat, 40V, 0,8A, 0,3W, 150MHz	41c	Rhm	2SC4485, 2SD1616
2SD2323	Si-N-Darl+Di	int. Z-Diode, 300/300V, 8A, 30W, B>500	17c	Hit	—
2SD2324	Si-N+Di	SMD, 20V, 0,8A, 150MHz, Rbe=1kΩ	35a	Say	—
2SD2328	Si-N-Darl	+Z-Di, 60V, 1A, 1,2W, 150MHz, B>6500	≈12b	Mat	—
2SD2328	Si-N	NF-L, 180/160V, 15A, 150W, 30MHz	77j	Mat	2SC3281, 2SD1975, 2SD2155
2SD2329		HA, 1500/600V, 5A, -IBp=2,5A, 80W	18c(j)	Mat	BU508A(F), BU706(F), BU908(F), ++
2SD232A	Si-N	=2SD231: 160V	23a		BDW32, BDY58, 2N6276..6277
2SD2330	Si-N	HA, 1500/600V, 7A, 100W	18c(j)	Mat	BU508A(F), BU2508A(F), BU908(F),++
2SD2331	Si-N+Di	HA, 1500/600V, 3A, -IBp=2A, 60W	18c	Mat	BU705DF, 2SD1554, 2SD1650, 2SD2089
2SD2332	Si-N	HA, 1500/600V, 3A, -IBp=2A, 60W	18c	Mat	BU705F, 2SD1544, 2SD1654, 2SD1883,++
2SD2333	Si-N+Di	HA, 1500/600V, 5A, -IBp=2,5A, 60W	18c	Mat	BU508DF, BU706DF, 2SD1555, 2SD2125,++
2SD2334	Si-N	HA, 1500/600V, 5A, -IBp=2,5A, 80W	18c	Mat	BU508AF, BU706F, 2SD1655, 2SD1864,++
2SD2335	Si-N+Di	HA, 1500/600V, 7A, -IBp=3A, 100W	18c	Mat	BU506DF, 2SD1555, 2SD2095, 2SD2125,++

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2SD2336	Si-N	HA, 1500/600V, 7A, -IBp=3A, 100W	18c	Mat	BU508AF, BU2508AF, 2SD1547, 2SD2252,++
2SD2337	Si-N	NF-L, 200/150V, 2A, 20W	17c	Hit	2SC3298B, 2SC4382, 2SD1587
2SD234	Si-N	NF/S-L, 60V, 3A, 25W, 3MHz	17j	Mic,Tos	BD241A, BD539A, BD535, BD935,++
2SD2340	Si-N-Darl	NF/S-L, 130/110V, 6A, 50W, 20MHz, B>5k	18j	Mat	2SD2221, 2SD2255
2SD2341	Si-N	Uni, 200/180V, 2A, 1,5W, 150MHz	78b	Mat	—
2SD2342	Si-N	NF/S-L, 150/80V, 6A, 50W	18j	Hit	BD245D..F, 2SC2837, 2SC4467, 2SD1046..47
2SD2343	Si-N	NF/S-L, 120V, 1,5A, 5W, 80MHz	14b	Rhm	2SC3821, 2SD1684, (2SC2690(A), 2SD1563)
2SD2344	Si-N	NF/S-L, 350/150V, 7A, 20W	17c	Hit	BU306F, BU406F, 2SC4130, 2SC4160,++
2SD2345	Si-N	=2SD1010: SMD	35a(1,6mm)	Mat	—
2SD2348	Si-N+Di	CTV-HA, 1500/600V, ±8A, 50W	18c	Tos	BU508DF, BU2508DF, 2SC4124, 2SD1880,++
2SD2349	Si-N+Di	CTV-HA, 1500/600V, ±10A, 50W	18c	Tos	BU2520DF, 2SC4125, 2SC4531, 2SD1881,++
2SD235	Si-N	=2SD234: 50V	17j	Mic,Tos	BD241, BD539A, BD535, BD935,++
2SD2350	Si-N-Darl	300/300V, 6A, 40W, B>500	17j	Fjd	2SD1071, 2SD1113, 2SD1307, 2SD1976
2SD2351	Si-N	=2SD2227S: SMD	35a(2mm)	Rhm	2SC4413
2SD2352	Si-N	hi-beta, 60V, 2A, 25W, 17MHz, B>600	17c	Tos	2SC3852, 2SD1776(A), 2SD1944, 2SD2158(A)
2SD2353	Si-N	hi-beta, 60V, 3A, 25W, 18MHz, B>800	17c	Tos	2SC3852, 2SD1972, 2SD1944, 2SD2127,++
2SD2354	Si-N	HA, 1500V, 7A, -IBp=3A, 100W	16c(j)	Mat	BU508A(F), BU908(F), BU2508A(F),++
2SD2355	Si-N	HA, 1500V, 10A, -IBp=4A, 100W	18c(j)	Mat	BU2520A(F), BU2525A(F)
2SD2356	Si-N	HA(64kHz), 1500V, 20A, 200W	17j	Mat	2SC3997, 2SC4290A
2SD2357	Si-N	SMD, lo-sat, 1V, 1A, 120MHz	39b	Mat	2SC2982, 2SC3443, 2SD1621
2SD2359	Si-N	SMD, lo-sat, 20V, 1A, 100MHz	39b	Mat	2SC2982, 2SC3443, 2SD1621
2SD238	Si-N	NF/S-L, 40V, 1,5A, 10W	22a	Sak	BD239, BD241, BD933, 2N4231..33,++
2SD2381	Si-N	Uni, 60V, 1A, 1,2W, 150MHz	≈12b	Mat	(BD517, BD525, 2SC2194, 2SD1801,++)
2SD2382	Si-N	Uni, 50V, 2A, 1,2W, 130MHz	≈12b	Mat	(BD509, BD515, 2SC3076, 2SD1801,++)
2SD2383	Si-N	Uni, 60V, 3A, 1,2W, 25MHz	≈12b	Mat	(2SC3386, 2SD1221, 2SD1802, 2SD1805,++)
2SD2364	Si-N	Uni, 80V, 1A, 1,2W, 140MHz	≈12b	Mat	(BD519, BD527, BD529, 2SC4135,++)
2SD2365	Si-N	Uni, 150V, 1A, 1,2W, C752690MHz	≈12b	Mat	(2SC2364, 2SC2983, 2SD1220, 2SD1918,++)
2SD2366	Si-N	S, 400/400V, 0,5A, 1,2W, 30MHz	≈12b	Mat	(2SC2752, 2SC3362, 2SC46152SD1053)
2SD2387	Si-N+Di	HA, 1500V, 3A, -IBp=2,5A, 50W	18c	Mat	BU705DF, 2SD1554, 2SD1877, 2SD2089,++
2SD2368	Si-N+Di	HA, 1500/700V, 3,5A, 60W	18c	Mat	BU706DF, 2SD1554, 2SD1877, 2SD2089,++
2SD2369	Si-N+Di	HA, 1500V, 4A, -IBp=2,5A, 70W	18c	Mat	BU706DF, 2SD1555, 2SD2095, 2SD2125,++
2SD237	Si-N	=2SD238: 80V	22a	Sak	BD239B, BD241B, BD937, 2N4233,++
2SD2370	Si-N+Di	HA, 1500/700V, 5A, 100W	18c	Mat	BU706DF, 2SD1555, 2SD2095, 2SD2125,++
2SD2371	Si-N+Di	HA, 1500V, 7A, 100W	18c	Mat	BU508DF, 2SC3693A, 2SC4124, 2SD1880,++
2SD2372	Si-N	HA, 1500/600V, 7A, -IBp=3A, 100W	18c	Mat	BU508AF, 2SC3895, 2SC4757, 2SD2252,++
2SD2373	Si-N	HA, 1500/600V, 10A, -IBp=4A, 100W	18c	Mat	BUH715, 2SC3697, 2SC4542, 2SD1887,++
2SD2374	Si-N	S-L, 60V, 3A, 25W, 30MHz, 500/2900ns	17c	Mat	2SD1762, 2SD1913, 2SC3690
2SD2375	Si-N	hi-beta, 80V, 3A, 25W, 50MHz, B>500	17c	Mat	2SD1273, 2SD1944, 2SD2092, 2SD2156
2SD238	Si-N	=2SD236: 110V	22a	Sak	BD239C, BD241C, BD939, 2SD381..382,++
2SD2381	Si-N	CTV-HA, 1500/800V, 3A, 40W	≈18c	Hit	BU706F, 2SD1544, 2SD1654, 2SD1883
2SD2383	Si-N	SMD, S, 400/300V, 20mA, 90MHz	35a	Nec	—
2SD2384	Si-N-Darl	NF/S-L, 140/140V, 7A, 100W, B>5000	77j	Tos	2SD2222, 2SD2250, 2SD2276
2SD2385	Si-N-Darl	NF/S-L, 140/140V, 8A, 120W, B>5000	77j	Tos	2SD2222, 2SD2250, 2SD2276
2SD2388	Si-N-Darl	=2SD2364: 70W	18j	Tos	2SD2221, 2SD2255
2SD2387	Si-N-Darl	=2SD2385: 80W	18j	Tos	BDV67C..D, 2SD1210
2SD2388	Si-N-Darl+Di	=2SD2090: 1,2W	78b	Rhm	—
2SD2389	Si-N-Darl	NF-L, 160/150V, 8A, 80W, 90MHz, B>5k	18j	Sak	BDV67D, 2SD1123
2SD2390	Si-N-Darl	NF-L, 160/150V, 10A, 100W, 55MHz, B>5k	18j	Sak	BDV67D, 2SD1123, 2SD1027, 2SD1515
2SD2391	Si-N	SMD, NF, lo-sat, 60V, 2A, 210MHz	39b	Rhm	2SC4409
2SD2394	Si-N	NF-L, 60V, 3A, 25W, 8MHz	17c	Rhm	BD937F, BDT31F, 2SC3475, 2SC3651,++
2SD2395	Si-N	NF-L, 60V, 3A, 25W, 100MHz	17c	Rhm	BD935F, BDT31F, 2SD1585, 2SD1985,++
2SD2396	Si-N	=2SD1943: Iso, 30W	17c	Rhm	2SD1273, 2SD2092, 2SD2156, 2SD2375,++
2SD2397	Si-N-Darl+Di	=2SD1764	17c	Rhm	→2SD1764
2SD2396	Si-N-Darl+Di	NF-L, 100V, 2A, 20W, B=1k..10k	15c(A)	Rhm	2SD1828, 2SD1890, 2SD2129, 2SD2257,++
2SD2399	Si-N-Darl+Di	NF-L, 80V, 4A, 30W, 40MHz, B=1k..10k	15c(A)	Rhm	BDT61F, 2SD1414, 2SD1788, 2SD1933,++
2SD24	Si-N	Vid-L, 300V, 0,1A, 6W(Tc=70°), 25MHz	22a	Say	2SC1505..1507, 2SC1755..1757, 2SC1905,++
2SD2400	Si-N	NF-L, 120V, 1,5A, 20W, 80MHz	17c	Rhm	2SC3364, 2SC3564, 2SC4883(A), 2SD1763,++
2SD2400A	Si-N	=2SD2400: 160V	17c	Rhm	2SC3364, 2SC4159, 2SC4370, 2SC4883A,++
2SD2401	Si-N-Darl	NF-L, 160/150V, 12A, 150W, 55MHz, B>5k	20j	Sak	—
2SD2402	Si-N	SMD, lo-sat, 50V, 5A, 170MHz, 275/530ns	39b	Nec	2SD1828
2SD2403	Si-N	SMD, lo-sat, 80V, 3A, 130MHz, 150/665ns	39b	Nec	2SC4541
2SD2406	Si-N	Uni-L, 80V, 4A, 25W, 8MHz	17c	Tos	2SC3851, 2SC3691, 2SD1408, 2SD2000,++
2SD2407	Si-N	S-L, 60V, 3A, 10W, 220MHz, 500/2900ns	30j	Mat	2SC4522, 2SD1221, 2SD1760, 2SD1802,++
2SD2408	Si-N	S-L, 50V, 2A, 10W, 150MHz	30j	Mat	2SC3076, 2SD1078..1079, 2SD1801,++
2SD2409	Si-N	S-L, 50V, 5A, 10W, 80MHz	30j	Mat	2SC3072, 2SC3518, 2SC3592, 2SD1805,++
2SD241	Si-N	NF/S-L, 60V, 4A, 25W	22a	Sak	BD243A, BD535, BDW25, BDX25,++

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2SD2410	Si-N-Darl+Di	S-L, 100V, 2A, 10W, 20MHz, B=1k..10k	30j	Mat	2SD1980
2SD2411	Si-N-Darl+Di	S-L, 200V, 2A, 10W, B=1k..10k	30j	Mat	—
2SD2412	Si-N	S-L, 400/300V, 0,75A, 10W, 180MHz	30j	Mat	2SC3362, 2SC3632, 2SC4615, 2SD1053
2SD2413	Si-N	SMD, S, 400/400V, 0,1A, 40MHz	39b	Mat	2SC4548
2SD2414(SM)	Si-N	S-L, lo-sat, 100V, 7A, 40W, 10MHz	30j	Tos	2SD1257(A)
2SD2415	Si-N	int. Z-Di(E→C), 25V, 0,5A, 0,5W	7c	Hit	—
2SD242	Si-N	=2SD241: 90V	22a	Sak	BD243C, BD539B, BDW25, BDX25, ++
2SD2421	Si-N-Darl+Di	=2SD2422: 1,8W	78c	Rhm	—
2SD2422	Si-N-Darl+Di	L, 100/100V, 7A, 30W, 40MHz, B>1000	17c	Rhm	2SD1791, (BD647F, 2SC4062, 2SD1415)
2SD2423	Si-N-Darl+Di	SMD, int. Z-Di(B→C), 50V, 1,5A, B>2000	39b(H)	Hit	—
2SD2425	Si-N	SMD, S, 80V, 5A, 600/880ns	39b	Nec	2SD2098, 2SD2402
2SD2426	Si-N-Darl	Uni, 100/80V, 2A, 1,5W, 80MHz	≈12b	Say	—
2SD2428	Si-N+Di	CTV-HA, Double Scan, 1700/600V, 8A, 200W	77j	Tos	(S3934..35, 2SC4532, 2SC4608)
2SD243	Si-N	=2SD241: 110V	22a	Sak	BD243C, BD539C, BDW25, BDX25, ++
2SD2432	Si-N	=2SD602:	35d	Mat	→2SD602
2SD2433	Si-N	=2SD1030:	35d	Mat	→2SD1030
2SD2434	Si-N-Darl	=2SD1478:	35d	Mat	→2SD1478
2SD2436	Si-N	=2SD1328:	35d	Mat	→2SD1328
2SD2437	Si-N-Darl+Di	NF-L, 120/120V, 6A, 60W, 80MHz, B>2k	18c	Sak	2SD1893..95, 2SD2045
2SD2438	Si-N-Darl+Di	NF-L, 160/150V, 6A, 70W, 80MHz, B>5k	18c	Sak	2SD1894..95, (2SD2221, 2SD2255)
2SD2439	Si-N-Darl+Di	NF-L, 160/150V, 10A, 70W, 55MHz, B>5k	18c	Sak	2SD1895, (2SD2390)
2SD244	Si-N	=2SD241: 130V	22a	Sak	BD243D, BDW25, BDX25, 2SD960..961, +
2SD2440	Si-N	hi-Ueb, hi-beta, 100V, 5A, 40W, 5MHz	18c	Tos	—
2SD2441	Si-N	SMD, lo-sat, 10V, 1,5A, 190MHz	39b	Mat	2SC2962, 2SC3443, 2SD1621
2SD2443	Si-N-Darl	L, 20V, 0,7A, 10W, B>1000, 150MHz	30j	Mat	2SC2871, 2SC4500, 2SD1598, 2SD1800
2SD2449	Si-N-Darl	L, 160/180V, 10A, 150W, 30MHz, B>3000	77j	Tos	—
2SD2450	Si-N	NF-Tr/E, -/32V, 2A, 0,9W	7c(9mm)	Rhm	2SC4145, 2SD1207, 2SD2069
2SD2451	Si-N	NF-Tr/E, -/180V, 1,5A, 0,9W	7c(9mm)	Rhm	2SC4814, 2SD1665A, 2SD1812, 2SD1857A
2SD2452	Si-N-Darl+Di	Z-Di(B→C), ±31V, 2A, 1,2W, B>1000	78b	Rhm	—
2SD2453	Si-N-Darl	NF/S-L80V, 3A, 10W, 100MHz, B>500	30j	Mat	2SD1223, 2SD1520, 2SD1817, 2SD1955
2SD2454	Si-N+Di	CTV-HA, 1700/600V, 7A, 50W	18c	Tos	BUH517D, 2SC4963
2SD2457	Si-N	SMD, 50V, 1,5A, 150MHz	39b	Mat	2SC2873, 2SD1623..24
2SD246	Si-N	TV-HA, 1500V, 4,5A, 18W(Tc=90°)	23a	Mat	BU208..209(A), BU508(A), 2SC2928, ++
2SD2461	Si-N	hi-beta, 80V, 2A, 1,3W, B>800	12b	Tos	(2SC3608)
2SD2462	Si-N	hi-beta, 60/80V, 3A, 1,3W, B>800	12b	Tos	(2SD1894)
2SD2463	Si-N-Darl+Di	Int. Z-Di(B→C), 31V, ±2A, 1W, B>2000	9b	Nec	—
2SD2464	Si-N	lo-sat, 15V, 5A, 0,75W, 170MHz, B>300	7c	Mat	2SC4482, 2SD1145
2SD2465	Si-N	L, lo-sat, 40V, 4A, 25W, 120MHz	17c	Mat	2SC3299, 2SC3746, 2SC4881
2SD2465A	Si-N	=2SD2465: 50V	17c		2SC3299, 2SC3746, 2SC4881
2SD2466	Si-N	L, lo-sat, 40V, 10A, 40W, 120MHz	17c	Mat	2SC3709, 2SC4064..65, 2SD1445(A)
2SD2466A	Si-N	=2SD2466: 50V	17c		2SC3709, 2SC4064..65, 2SD1445A
2SD2467	Si-N	=2SD1254:	17c	Mat	→2SD1268
2SD2468	Si-N	=2SD1255:	17c	Mat	→2SD1269
2SD2469(A)	Si-N	=2SD1257(A):	17c	Mat	→2SD1271(A)
2SD247	Si-N	NF/S-L, 80V, 5A, 50W	23a	Old	BD245B, BDV93, BDX93, 2N5632..33, ++
2SD2470	Si-N	Blitzg./Strobo, -/10V, 5A, 0,4W	41c	Rhm	2SD1244, 2SD1934, 2SD2249, 2SD2497, ++
2SD2472	Si-N	SMD, lo-sat, 10V, 0,5A, 120MHz	35d	Mat	2SC4577
2SD2473	Si-N	SMD, lo-sat, 20V, 0,5A	35d	Mat	2SC4519, 2SC4577
2SD2474	Si-N	SMD, lo-sat, 10V, 2A, 180MHz	39b	Mat	2SC3443, 2SC2962, 2SD1621
2SD2476	Si-N-Darl	L, 80/80V, 4A, 30W, 40MHz, B>1000	17c	Rhm	2SD1788, (BDT61BF, 2SD1414, 2SD1589++)
2SD2479	Si-N-Darl	L, 120V, 2A, 1,5W, 150MHz, B>4000	78b	Mat	—
2SD2480	Si-N-Darl+Di	100V, 2A, 1,3W, 100MHz, B>2000	12b	Tos	(2SD1980, 2SD2410)
2SD2481	Si-N-Darl+Di	30V, 1,5A, 1,3W, B>4000, 180/900ns	12b	Tos	(2SD947)
2SD2482	Si-N	=2SD2472:	35a(2mm)	Mat	2SC4555
2SD2483	Si-N	=2SD2473:	35a(2mm)	Mat	2SC4555
2SD2484	Si-N	lo-sat, 50V, 2A, 0,9W	7c(9mm)	Hit	2SC3728, 2SD1207, 2SD2069, 2SD2177, ++
2SD2485	Si-N	=2SD2484: 80V	7c(9mm)	Hit	2SC3328, 2SC4489, 2SD2182
2SD2486	Si-N	hi-beta, lo-sat, 80V, 5A, 70MHz, B>500	17c	Mat	2SD1948, 2SD2075..2078
2SD2488	Si-N-Darl	L, 200/200V, 15A, 130W, 70MHz, B>5000	18j	Sak	—
2SD2489	Si-N-Darl	=2SD2488: 17A, 200W	20j	Sak	—
2SD249	Si-N	NF/S-L, 50V, 30A, 125W, 0,8MHz	23a	Fui	BDX41, 2N3771, 2SD630
2SD2490	Si-N-Darl	=2SD2488: Iso, 85W	18c	Sak	—
2SD2491	Si-N	Vid-E, 160/180V, 0,1A, 8W, 140MHz	14b	Hit	2SC3788, 2SC3955..56
2SD2492	Si-N	=2SD2491: 200/200V	14b	Hit	2SC3788, 2SC3955..56
2SD2493	Si-N-Darl	NF-L, 110/110V, 6A, 60W, 80MHz, B>5000	18j	Sak	2SD2340, 2SD2386
2SD2494	Si-N-Darl	=2SD2493: Iso	18c	Sak	2SD1893..94, 2SD2438

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2SD2495	Si-N-Darl	=2SD2493: Iso, 30W	17c	Sak	2SD2025
2SD2496	Si-N	=2SD601A:	35d	Mat	→2SD601A
2SD2497	Si-N	Io-sat, 40/20V, 5A, 0,75W	7c	Hit	2SC4482, 2SD1145, (2SD1244, 2SD2249++)
2SD2498	Si-N	CTV-HA, 1500/600V, 6A, 50W	18c	Tos	BU2508AF, 2SC3884A, 2SC3894, 2SC4830,++
2SD2499	Si-N+Di	CTV-HA, 1500/600V, 6A, 50W	18c	Tos	2SC4764
2SD24Y	Si-N	=2SD24: 0,15A, 8MHz	22a		2SC1505..1507, 2SC1755..1757, 2SC1905,++
2SD25	Ge-N	NF, 25V, 0,1A, 0,11W	2a	Nec	AC127, AC178, AC187, 2SD30
2SD250	Si-N	=2SD249: 100V, 0,6MHz	23a	Fui	BDY29, MJ802, 2SD797
2SD2500	Si-N	TV-HA, 1500/600V, 10A, 50W	18c	Tos	BU2520AF, BUH715, 2SC4542, 2SC4759,++
2SD2504	Si-N	Io-sat, 15V, 5A, 0,75W, 170MHz, B>300	7c	Mat	2SC4482, 2SD1145
2SD251	Si-N	NF/S-L, 200V, 2A, 30W, -/7,5µs	22a	Fui	BD239F, BUX67, 2SD610, 2SD1138,++
2SD2510	Si-N	HA, 1500V, 3A, 60W	18c	Mat	BU706F, 2SD1544, 2SD1653, 2SD1882,++
2SD2511	Si-N	HA, 1500V, 3A, 60W	18c	Mat	BU706F, 2SD1544, 2SD1653, 2SD1882,++
2SD2512	Si-N	HA, 1500V, 5A, 60W	18c	Mat	BU706F, 2SC4830, 2SD1545, 2SD1655,++
2SD2513	Si-N	HA, 1500V, 5A, 60W	18c	Mat	BU706F, 2SC4830, 2SD1545, 2SD1655,++
2SD2514	Si-N	HA, 1500V, 7A, 100W	18c	Mat	BU2508AF, 2SC3895, 2SC4757, 2SD2252,++
2SD2515	Si-N	HA, 1500V, 7A, 100W	18c	Mat	BU2508AF, 2SC3895, 2SC4757, 2SD2252,++
2SD2521	Si-N	HA, 1700V, 2,5A, 60W	18c	Mat	2SC4761, 2SC4796
2SD2522	Si-N	HA, 1700V, 4A, 80W	18c	Mat	2SC4761, 2SC4796
2SD2523	Si-N	HA, 1700V, 6A, 90W	18c	Mat	BUH417, BUH517, 2SC4797
2SD2524	Si-N	HA, 1700V, 8A, 100W	18c	Mat	BUH517, 2SC4797
2SD2525	Si-N	NF, 60V, 3A, 1,8W, 3MHz	15c	Tos	2SD1683, (BD785, 2SD1508, 2SB1818)
2SD2526	Si-N-Darl+Di	100V, 6A, 1,8W, B=2k..15k	15c	Tos	—
2SD2529	Si-N	=2SD1938:	35d	Mat	→2SD1938
2SD2531	Si-N	NF-L, 60V, C76634A, 25W, 3MHz	17c	Tos	BD949F, 2SC3299, 2SC3746, 2SD1687,++
2SD2532	Si-N	=2SD2464: SMD	39b	Hit	2SC4409, 2SC4541, 2SD1623..24
2SD2533	Si-N	=2SD2465: SMD	39b	Hit	2SC4409, 2SC4541
2SD2538	Si-N-Darl+Di	int. Z-Di(B2→C), 85V, 2A, 0,9W, B>2k	7c(9mm)	Tos	—
2SD2536	Si-N-Darl+Di	Rb=3,6k, Rbe=5kΩ			—
2SD2539	Si-N+Di	CTV-HA, 1500/600V, 7A, 50W	18c	Tos	BU2506DF, 2SC3892A, 2SC4123, 2SD2251,++
2SD254	Si-N	NF-L, 70V, 2A, 20W	22a	Nec	BD241A, BD537, BD937, BDY78,++
2SD2540	Si-N	=2SD2497: SMD	39b	Hit	2SD1628
2SD2544	Si-N	=2SD2496: 15W	78c	Mat	(→2SD2486)
2SD255	Si-N	NF-L, 70V, 2A, 20W	22a	Nec	BD241A, BD537, BD937, BDY78,++
2SD2553	Si-N	HA, 1700/600V, 6A, 50W	18c	Tos	BUH517, 2SC4797
2SD2557	Si-N-Darl	S-L, S-Reg, 200/200V, 5A, 70W, B>1500	18j	Sak	—
2SD2558	Si-N-Darl	=2SD2557: Iso, 60W	18c		—
2SD258	Si-N	NF/S-L, 60V, 4A, 25W, 1270/3300ns	22a	Sak	BD243A, BD535, BD539A, BDY79,++
2SD2560	Si-N-Darl	S-L, S-Reg, 150/150V, 15A, 130W, B>5k	18j	Sak	(BDV67D)
2SD2561	Si-N-Darl	=2SD2560: 17A, 200W	20j	Sak	—
2SD2562	Si-N-Darl	=2SD2560: Iso, 65W	18c	Sak	(BDV67DF)
2SD2562					2SF
2SD257	Si-N	=2SD258: 90V	22a	Sak	BD243B, BD539C, 2SD712, BDY79,++
2SD258	Si-N	=2SD258: 110V	22a	Sak	BD243C, BD539D, BD955, BDY79,++
2SD259	Si-N	=2SD258: 130V	22a	Sak	BD243D, BD941, 2SC2518, 2SD960..961,++
2SD26	Si-N	NF/S-L, 40V, 7A, 50W	23a	Hit	BD245, BDV91, BDX91, 2N5873..5874,++
2SD260	Si-N	NF/S-L, 100V, 5A, 50W	23a	old	BD245C, BDV95, BDX95, 2N5632..33,++
2SD261	Si-N	Uni, 40V, 0,5A, 0,5W, 160MHz	7c*	Nec,Mic	BC337, BC535, BC637, BC639,++
2SD262	Si-N	S-L, 300/140V, 12A, 125W	23a	Son	BUW7475, BUX42, MJ15022, 2SC3043,++
2SD265	Si-N	S-L, 800/400V, 6A, 100W, B>15	23a	Org	BU326(A), BU426(A), BU526, BUX47,++
2SD266	Si-N	=2SD265: B>30	23a	Org	BU326(A), BU426(A), BU526, BUX47,++
2SD26A	Si-N	=2SD26: 60V	23a		BD245A, BDV91, BDX91, 2N5873..5874,++
2SD26B	Si-N	=2SD26: 100V	23a		BD245C, BDV95, BDX95, 2N5632..5833,++
2SD26C	Si-N	=2SD26: 150V	23a		BD245D, BDX11, 2N3442, 2SD731..732,++
2SD27	Ge-N	NF-Tr/E, 32V, 0,5A, 0,28W	2a	Mat	AC127, AC178, AC187, 2SD72, 2SD352
2SD271	Si-N	S-L, 300/400V, 2A, 30W, B>15	22a	Org	BUV36(A), BUX84..65, 2SC3531
2SD272	Si-N	=2SD271: B>30	22a	Drg	BUV36(A), BUX64..65, 2SC3531
2SD273	Si-N	S-L, 800/400V, 5A, 60W, B>15	23a	Org	BU426(A), BUS11(A), BUW11(A),++
2SD274	Si-N	=2SD273: B>30	23a	Org	BU426(A), BUS11(A), BUW11(A),++
2SD26	Si-N	NF/S-L, 70/40V, 3A, 18W	22a	Son	BD241A, BD537, BD937, 2SD712,++
2SD260	Si-N-Darl	S-L, 600/300V, 6A, 100W, B>350	23a	Org	BUW81, MJ10013..14, 2SD605, 2SD705,++
2SD283	Si-N	NF/S-L, 120V, 5A, 25W, B>42	22a	Nec	BD243C, BD539D, BD955, 2SD961,++
2SD264	Si-N	=2SD283: 20MHz, B>25	22a	Nec	BD243C, BD539D, BD955, 2SD961,++
2SD285	Si-N	=2SD283: 100V	22a	Nec	BD243C, BD539C, BD953, 2SD613,++
2SD296	Si-N	NF/S-L, 180/100V, 10A, 100W	23a	Nec	BD245E, 2SC2607..06, 2SC3263, 2SD665,++
2SD287(A..C)	Si-N	NF/S-L, 200/120V, 10A, 100W, 8MHz	23a	Nec	BD245F, 2SC2607..08, 2SC3263, 2SD665++

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2SD288	Si-N	NF/S-L, 80V, 3A, 20W, 35MHz	17j	Nec, Mic	2SC3252, (BD241B, BD537, BD937, ++)
2SD289	Si-N	=2SD288:	17j	Nec, Mic	2SC3252, (BD241B, BD537, BD937, ++)
2SD29	Si-N	=2SD28: 70/60V	22a	Son	BD241B, BD537, BD937, 2SD712, ++
2SD290	Si-N	NF/S-L, 80V, 5A, 23W, 10MHz	22a	Son	BD243B, BD539B, BD951, 2N4233A, ++
2SD291	Si-N	NF/S-L, 70/40V, 3A, 18W, 4MHz	22a	Son	BD241A, BD537, BD937, 2N4232..33, ++
2SD292	Si-N	=2SD291: 70/55V	22a	Son	BD241A, BD537, BD937, 2N4232..33, ++
2SD293	Si-N	S-L, 800/400V, 10A, 125W, B>14	23a	Org	BUS12(A), BUW26, BUW35..36, BUX81, ++
2SD294	Si-N	=2SD293: B>26	23a	Org	BUS12(A), BUW26, BUW35..36, BUX81, ++
2SD295	Si-N	S-L, 800/400V, 30A, 200W, B>15	68a	Org	2SC2204, 2SC2977
2SD296	Si-N	=2SD295: B>30	68a	Org	2SC2204, 2SC2977
2SD297	Si-N	S-L, 150/80V, 3A, 25W, 40MHz	22a	Nec	BD241D, 2N3441, 2SCS2516, 2SD772(A,B), ++
2SD299	Si-N	TV-HA, 1500V, 5A, 16W(Tc=90°), B>2	23a	Mat	BU208(A), BU508(A), 2SC2928, 2SD820, ++
2SD30	Ge-N	NF-Tr/E, 25V, 0,2A, 0,3W	2a*	Say	AC127, AC176(K), AC187(K), 2SD72
2SD300	Si-N	=2SD299: B>3	23a	Mat	BU208(A), BU508(A), 2SC2928, 29D820, ++
2SD301	Si-N-Darl	NF/S-L, 400V, 30A, 50W, B=2500	23a(G)	Fui	BDV65A, BDX83B, BDX85B, MJ3001, ++
2SD31	Ge-N	NF, 25V, 0,125A, 0,125W, B=50	2a	Mat	AC127, AC176, AC187, 2SD30, 2SD72
2SD310	Si-N	S-L, 800/400V, 15A, 150W, B>15	23a	Org	BUS13(A), BUW45..46, BUX46(A..C)
2SD311	Si-N	=2SD310: B>30	23a	Org	BUS13(A), BUW45..46, BUX48(A..C)
2SD312	Si-N	S-L, 800/600V, 0,5A, 25W(Tc=100°)	23a	Mat	2SC3151
2SD313	Si-N	NF/S-L, 80V, 3A, 30W, 8MHz	17j	Say, Mic	BD241A, BD535, BD539A, BD935, ++
2SD314	Si-N	=2SD313:	17j	Say, Mic	BD241A, BD535, BD539A, BD935, ++
2SD315	Si-N	=2SD313: 4A, 35W	22a	Say	BD243A, BD535, BD539A, 2N4232..33A, ++
2SD316(-1,-2)	Si-N	NF/S-L, 80..100V, 7A, 80W, 12MHz	23a	Son	BD245C, BDV95, BDX95, 2N5632..33, ++
2SD317	Si-N	NF/S-L, 60V, 3A, 25W	17j	Mat	BD241A, BD535, BD539A, BD935, ++
2SD317A	Si-N	=2SD317: 80V	17j		BD241B, BD537, BD539B, BD937, ++
2SD318	Si-N	=2SD317:	17j	Mat	BD241A, BD535, BD539A, BD935, ++
2SD318A	Si-N	=2SD318: 80V	17j		BD241B, BD537, BD539B, BD937, ++
2SD319	Si-N	NF/S-L, CTV, 110V, 10A, 100W, 1MHz	23a	Mat	BD317, 2N3055, 2N5632..33, 2SD426, ++
2SD32	Ge-N	=2SD31: B=90	2a	Mat	AC127, AC176, AC187, 2SD30, 2SD73
2SD320	Si-N	S-L, 300/230V, 2A, 50W	23a	Say	2SC1463, 2SC2609, 2SD632
2SD321	Si-N	S-L, 250V, 6A, 80W, 8MHz	23a	Mat	BU606..608, BUX18(A..C), 2SD1154, ++
2SD322	Si-N	NF/S-L, 120/80V, 7A, 80W	23a	Nec	BD245D, 2N3442, 2SD551, 2SD731..733, ++
2SD323	Si-N	=2SD322: 150/100V	23a	Nec	BD245D, 2N3442, 2SD551, 2SD731..733, ++
2SD324	Si-N	Vid-L, 300V, 0,1A, 10W(Tc=70°)	22a	Mat	2SC1505..1507, 2SC1755..1757, 29C1819, ++
2SD325	Si-N	NF/S-L, 35V, 1,5A, 10W, 8MHz	17j	Say	BD239, BD241, BD533, BD933, ++
2SD326	Si-N	S-L, 330/220V, 1A, 23W, 6,5MHz	22a	Son	TIP47..50, 2SC782, 2SC887, 2SD859, ++
2SD327	Si-N	Uni, 40V, 0,5A, 0,25W, 120MHz	7c	Nec, Mic	BC337, BC635, BC637, BC639, ++
2SD328	Si-N	NF/S, 100V, 1A, 0,8W, 50MHz	2a	Nec	BC141, 2N1990, 2N2102, 2N2405, ++
2SD329	Si-N	NF/S, 70V, 1A, 0,8W, 30MHz, -/6,5µs	2a	Fui	BC140..141, 2N1990, 2N2102, 2N2405, ++
2SD33	Ge-N	NF, 20V, 0,05A, 0,15W	2a	Fui	AC127, 2SD30
2SD330	Si-N	NF/S-L, 50V, 2A, 20W, 8MHz	17j	Say, Mic	BD239, BD241, BD535, BD935, ++
2SD331	Si-N	=2SD330:	17j	Say, Mic	BD239, BD241, BD535, BD935, ++
2SD332	Si-N	NF/S-L, 130V, 7A, 65W, 30MHz	23a	Say	BD245D, 2N3442, 2SD551, 2SD731..733, ++
2SD334	Si-N	NF/S-L, 110V, 6A, 75W	23a	Mat	BD245C, 2N3442, 2SD551, 2SD731..733, ++
2SD334A	Si-N	=2SD334: 130V	23a		BD245D, 2N3442, 2SD551, 2SD731..733, ++
2SD335	Si-N	NF/S-L, 80V, 3A, 30W	23a	Nec	BD245B, BDV93, 2N4915, 2SD895..896, ++
2SD336	Si-N	Uni, NF-Tr/E, 40V, 0,5A, 0,75W	7c*	Nec	BC337, BC635, BC637, BC639, ++
2SD338(-1,-2)	Si-N	NF/S-L, 70..90V, 7A, 60W, >3MHz	23a	Son	BD245C, BDV95, BDX95, 2N5632..34, ++
2SD339(-1,-2)	Si-N	=2SD338: 90..110V, 10A, 80W	23a	Son	BD245C, BDV95, BDX95, 2N5632..34, ++
2SD34	Ge-N	NF, 20V, 0,15A, 0,25W	1a	Fui	AC127, AC176, AC187, 2SD30, 2SD72
2SD340(-1,-2)	Si-N	=2SD338: 110..140V, 12A, 100W	23a	Son	BD745E, 2N3442, 2SD551, 2SD733, ++
2SD341	Si-N	NF/S-L, 100V, 15A, 115W, >0,8MHz	23a	Hit	BD317, BDW10, 2N3056, 2SD1105, ++
2SD342	Si-N	NF/S-L, 70/40V, 3A, 35W	17j	Son	BD241A, BD537, BD539A, BD937, ++
2SD343	Si-N	=2SD342	17j	Son	BD241A, BD537, BD539A, BD937, ++
2SD344	Si-N	=2SD342: 70/55V	17j	Son	BD241A, BD537, BD539A, BD937, ++
2SD345	Si-N	=2SD342: 70/55V	17j	Son	BD241A, BD537, BD539A, BD937, ++
2SD346	Si-N	NF/S-L, 80V, 5A, 25W	17j	Son	BD243A, BD539A, BD543A, BD949, ++
2SD347	Si-N	=2SD346	17j	Son	BD243A, BD539A, BD543A, BD949, ++
2SD348	Si-N	TV-HA, 1500/400V, 7A, 50W	23a	Say	BU508(A), BU908, 2SC3027..3026
2SD349	Si-N	SMD, NF, 30V, 0,05A	35a	Nec	BC846..848, BCW31..33, 2SC1622, ++
2SD35	Ge-N	NF, 20V, 0,06A, 0,083W	37a	Mat	AC127, 2SD72
2SD350(A)	Si-N	TV-HA, 1500/700V, 5A, 22W(Tc=90°)	23a	Mat	BU208(A), BU508(A), 2SC2928, 2SD954, ++
2SD351	Si-N	S-L, 650/270V, 5A, 80W, 40MHz	23a	Mat	BU326(A), BU426(A), 2SC2962, 2SC3092++
2SD352	Ge-N	NF, 32V, 1A, 0,22W	2a	Mat	AC176
2SD353	Si-N	NF/S-L, TV-VA, 150V, 2A, 80W, 8MHz	23a	Say	2SC1195, 2SC2809, 2SD1136, 2SD1159, ++
2SD355	Si-N	Uni, 30V, 1A, 0,8W, 100MHz	7b	Mit	BC337..338, BC635, BC637, BC639, ++

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2SD356	Si-N	NF/S-L, 90V, 0,8A, 10W, 70MHz	17j	Mit, Mic	2SC1913(A), 2SC2275(A), 2SC2591..92, ++
2SD357	Si-N	=2SD356: 110V	17j	Mit	2SC1913(A), 2SC2275(A), 2SC2591..92, ++
2SD358	Si-N	=2SD356: 130V	17j	Mit	2SC1913(A), 2SC2275(A), 2SC2591..92, ++
2SD359	Si-N	NF/S-L, 40V, 2A, 10W, 70MHz	17j	Mit, Mic	2SC1398, 2SC3252
2SD36	Ge-N	NF, 20V, 0,06A, 0,063W	37a	Mat	AC127, 2SD72
2SD360	Si-N	NF/S-L, 40V, 2A, 10W, 70MHz	17j	Mit, Mic	2SC1398, 2SC3252
2SD361	Si-N	NF/S-L, 60V, 1,5A, 10W, 70MHz	17j	Mit	2SC1398, 2SC3252
2SD362	Si-N	S-L, 150/100V, 5A, 40W, 15MHz	22a	Nec	BU406..409, MJE15030, 2SD772(A,B), ++
2SD363	Si-N	S-L, 250/200V, 30A, 200W, <2/10,5µs	88a	Nec	2SD374
2SD363A	Si-N	=2SD363: 350/300V	68a		2SD374
2SD364	Si-N	=2SD363: 450/400V	68a	Nec	2SD374
2SD365	Si-N	NF/S-L, 90V, 3A, 25W, >3MHz	17j	Mat, Mic	BD241A, BD535, BD539A, BD935, ++
2SD365A	Si-N	=2SD365: 80V	17j		BD241B, BD537, BD539B, BD937, ++
2SD366(A)	Si-N	=2SD365(A)	17j	Mat, Mic	→2SD365(A)
2SD367	Ge-N	NF, 25V, 0,3W, 0,15W	2a	Mat	AC127, AC178, AC187, 2SD72, 2SD352
2SD368	Si-N	TV-HA, 1500/1500V, 5A, 60W	23a	Say	BU207..208(A), BU508(A), 2SC2928, ++
2SD369	Si-N	NF/S-L, 90V, 10A, 100W, 2MHz	23a	Tos	BD315, BDW21C, 2N3055, 2N5632..34, ++
2SD37	Ge-N	NF, 30V, 0,05A, 0,15W	2a	Fui	AC127, 2SD30
2SD370	Si-N	NF/S-L, 110V, 8A, 80W	23a	Tos	BD245C, BD550, 2N3055, 2N5633..34, ++
2SD371	Si-N	NF/S-L, 100V, 8A, 50W, 5MHz	23a	Tos	BD245C, BDV95, BDX95, 2N5632..34, ++
2SD372	Si-N	S-L, 150/100V, 30A, 200W, 0,3/2µs	68a	Nec	2SD363
2SD373	Si-N	=2SD372: 250/200V	68a	Nec	2SD363
2SD373A	Si-N	=2SD372: 350/300V	68a		—
2SD374	Si-N	=2SD372: 450/400V	68a	Nec	—
2SD375	Si-N	S-L, 150/100V, 10A, 100W, 15MHz	23a	Nec	BUW70, BUX17(A..C), BUX43, BUY18, ++
2SD376	Si-N	=2SD375: 250/200V	23a	Nec	BUW72, BUX17(A..C), BUX43, BUY18, ++
2SD376A	Si-N	=2SD375: 350/300V	23a		BUW72, BUX14, BUX17AC, BUX43, ++
2SD377	Si-N	=2SD375: 450/400V	23a	Nec	BUW72, BUX14, BUX17C, 2SC3046, ++
2SD378	Si-N	NF/S, 100V, 2A, 1W	2a	Nec	BCX40, BSS15, BSV84, 2N5320, ++
2SD379	Si-N	NF/S-L, 60V, 5A, 60W, 10MHz	23a	Mat	BD245B, BD313, BDV93, BDX93, ++
2SD38	Ge-N	NF, 30V, 0,15A, 0,25W	1a	Fui	AC127, AC178, AC187, 2SD30, 2SD72
2SD380(A)	Si-N	TV-HA, 1500/700V, 5A, 50W(Tc=75°)	23a	Mat	BU208(A), BU508(A), 2SC2928, 2SD954, ++
2SD381	Si-N	NF/S-L, 130V, 1,5A, 20W, 45MHz	17j	Nec	2SC2236(A), 2SC2275(A), 2SD608(A), ++
2SD382	Si-N	=2SD381	17j	Nec	→2SD381
2SD383	Si-N	S-L, 300/300V, 5A, 100W	23a	Hit	BU606..608, BUX18A..C, BUY35, ++
2SD384	Si-N-Darl	NF/S-L, 90V, 7A, 30W, B>1500, <3/9µs	22a	Shi	BD847, BD899, BDW73B, BDX53B, ++
2SD385	Si-N-Darl	=2SD384: 100V	22a	Shi	BD849, BD901, BDW73C, BDX53C, ++
2SD386(A)	Si-N	TV-VA, 200/120V, 3A, 25W, 8MHz	17j	Say	BD241F, 2SD772A,B
2SD387(A)	Si-N	=2SD386(A): 2A	17j	Say	BD239F, 2SC2660, 2SD610, 2SD790, 2SD1136
2SD388	Si-N	NF/S-L, 160V, 8A, 80W, 9MHz	23a	Nec	BD245D, 2N3442, 2SD551, 2SD732..733, ++
2SD389	Si-N	NF/S-L, 60V, 3A, 25W	17j	Mat	BD241A, BD539A, BD535, BD935, ++
2SD389A	Si-N	=2SD389: 90V	17j		BD241B, BD539B, BD537, BD937, ++
2SD390(A)	Si-N	=2SD389(A)	17j	Mat	→2SD389(A)
2SD392	Si-N	Uni, 20V, 0,3A, 0,3W, 160MHz	7b	Mit	BC337..338, BC635, BC537, BC639, ++
2SD393	Si-N	S-L, 500/360V, 8A, 100W	23a	Mit	BU326(A), BU426(A), BUX15, 2SC3041, ++
2SD394	Si-N	S-L, 700/400V, 6A, 100W	23a	Mit	BU326(A), BU426(A), BUX47, 2SC3092, ++
2SD395	Si-N	S-L, 700/400V, 8A, 100W	23a	Mit	BU526(A), BUW26, BUW35..36, 2SC3049++
2SD396	Si-N	S-L, 700/300V, 15A, 125W, <15/40µs	23a	Hit	BUS13(A), BUW45..46, BUX48(A..C), ++
2SD400(MP)	Si-N	Uni, lo-sat, 25V, 1A, 0,9W, 180MHz	7c(9mm)	Say	2SC4483..85, 2SD1207
2SD400P1,P2	Si-N	=2SD400(MP): 1W	7c°		(BD505, BD515, BD525, 2SC2194, ++)
2SD401(A)	Si-N	TV-VA, 200V, 2A, 20W, 5MHz	17j	Nec	BD239F, 2SC2660, 2SD610, 2SD1136, ++
2SD402(A)	Si-N	=2SD401(A)	17j	Nec	→2SD401(A)
2SD404	Si-N	NF/S-L, 50V, 8A, 40W	17j	Tos	BD243A, BD543A, BD797, BD805, ++
2SD405	Si-N-Darl	NF/S, 70V, 2A, 1W, B>2000, 0,4/3µs	2a	Nec	2SC1878, 2SC1888, 2SD614..615, 2SD688
2SD406	Si-N-Darl	=2SD405: 100V	2a	Nec	2SC1879, 2SD614..615, 2SD688
2SD407	Si-N-Darl	NF/S-L, 100V, 5A, 25W, B=4000, 1,7/6µs	2a	Nec	(BD649, BD901, BDW23C, BDW63C, ++)
2SD408	Si-N-Darl	=2SD407: 150V, hFE=3000	2a	Nec	(2SD630, 2SD1128, 2SD1169, 2SD1590, ++)
2SD409	Si-N-Darl	=2SD407: 30W	23a	Nec	BD649, BD901, BDW23C, BDW63C, ++
2SD41	Si-N	NF/S-L, 90V, 10A, 200W	23a	Tos	BD315, BD317, 2N3772, 2N5629..31, ++
2SD410	Si-N-Darl	=2SD407: 150V, 30W, B=3000	23a(A)	Nec	2SD630, 2SD1128, 2SD1169, 2SD1590, ++
2SD411	Si-N-Darl	NF/S-L, 100V, 10A, 80W, B=4000, 1/7µs	23a	Nec	BDV85B, BDW83C, BDX83C, BDX85C, ++
2SD412	Si-N-Darl+Di	NF/S-L, 150V, 15A, 100W, B=4000	23a	Nec	2SD1296, 2SD1299
2SD413	Si-N	S/Vid, 200V, 0,5A, 0,8W, 25MHz	2a	Fui	2SD578, 2SD624, (BF757..759, MPS-U10++)
2SD414	Si-N	NF-L, 120/90V, 0,8A, 10W, 45MHz	14h	Nec	2SC2690(A), 2SD1382, 2SD1563(A)
2SD415	Si-N	=2SD414: 120/100V	14h	Nec	2SC2690(A), 2SD1382, 2SD1563(A)
2SD418	Si-N	TV-HA, 1500/400V, 7A, 50W	23a	Say	BU508(A), BU908, 2SC3027..3028

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2SD417	Si-N	S-L, 250/200V, 7A, 75W, 30MHz	23a	Fui	BU606..606, BUX18(A..C), 2SD1154, ++
2SD418	Si-N	TV-HA, 1000/500V, 5A, 80W	23a	Mat	BU207..208(A), BU508(A), 2SC1413, ++
2SD419	Si-N-Darl	NF/S-L, 100V, 7A, 40W, 6MHz, B=2500	22a	Sak	BD649, BD901, BDW73C, BDX53C, ++
2SD420	Si-N-Darl	=2SD419: 120V	22a	Sak	BD651, BDT21, BDW73D, BDX53E, ++
2SD421	Si-N-Darl	=2SD419: 140V	22a	Sak	BDX53E, F, 2SD1386, 2SD1590..1591
2SD422	Si-N	S-L, 250/200V, 4A, 30W, 30MHz	22a	Fui	BU406..409, 2N6233..35, 2SC2767, ++
2SD423	Si-N	S-L, 250/200V, 4A, 30W, 30MHz	22a	Fui	BU406..409, 2N6233..35, 2SC2767, ++
2SD424	Si-N	HiFi-NF-E, 160V, 15A, 150W, 5MHz	23a	Tos	BDW12, MJ15015, 2N3773, 2SC2607..2608++
2SD425	Si-N	HiFi-NF-E, 140V, 12A, 100W	23a	Tos	BDW12, BDY54, 2SC1584, 2SD551, ++
2SD426	Si-N	HiFi-NF-E, 120V, 12A, 100W, 5MHz	23a	Tos	BDW10, 2SD551, 2SD733, 2SD1105, ++
2SD427(S)	Si-N	HiFi-NF-E, 120V, 8A, 80 100W, 5MHz	23a	Tos	BD550, 2N5633..34, 2SD551, 2SD733, ++
2SD428	Si-N	HiFi-NF-E, 100V, 7A, 80W, 7MHz	23a	Tos	BD245C, BDV95, BDX95, 2N5632..33, ++
2SD429	Si-N	S-L, 800/400V, 15A, 100W, <20/15µs	23a	Hit	BUS13(A), BUW45..46, BUX48(A..C), ++
2SD43	Ge-N	NF, 25V, 0,05A, 0,11W	2a	Tos	AC127, 2SD30
2SD430	Si-N	S-L, 120V, 5A, 50W, 15MHz	23a	old	BD245D, 2N4347, 2N5759, 2SD896, ++
2SD431	Si-N	S-L, 120V, 7A, 80W, 20MHz	23a	old	BD245D, 2N4348, 2N5633..34, 2SD718, ++
2SD432	Si-N	S-L, 130V, 10A, 100W, 15MHz	23a	old	BD245D, 2N3442, 2SD551, 2SD733, ++
2SD433	Si-N	S-L, 250V, 10A, 100W, 15MHz	23a	old	BUX17(A..C), 2SC1586, 2SD555, 2SD583, ++
2SD434	Si-N	S-L, 200/200V, 20A, 200W	23a	old	BUV11..12, BUW58, BUW73, BUX11..12
2SD435	Si-N	=2SD434: 300/300V	23a	old	BUV12, BUV24, BUW73, BUX12, BUX24
2SD436	Si-N	=2SD434: 400/400V	23a	old	BUV24, BUX24, 2SC3085
2SD437(W)	Si-N	S-L, 800/350V, 10A, 80W, 2,5MHz	23a	Say	BUW12(A), BUW25..26, BUX80, 2SC3046++
2SD438(MP)	Si-N	Uni, lo-sat, 100V, 0,7A, 0,9W, 100MHz	7c(9mm)	Say	2SC4488, 2SC4489, 2SD667, 2SD1812
2SD439	Si-N	NF/S-L, lo-sat, 20V, 1,2A, 8W, 150MHz	14h	Say	BD135, BD226, BD375, 2SD1380, ++
2SD43A	Ge-N	=2SD43: 45V, 0,15A	2a		—
2SD44	Ge-N	NF, 30V, 0,05A, 0,08W	2a	Tos	AC127, 2SD30
2SD445	Si-N-Darl	S-L, 350/300V, 4A, 60W, B>350	23a	Org	BUX28..29, 2SD850, 2SD706, 2SD1043, ++
2SD45	Si-N	NF/S-L, 150/100V, 5A, 50W, 20MHz	23a	Son	BD245D, BDX11, 2N3442, 2SD551, 2SD732, +
2SD457	Si-N	S-L, 250/200V, 55A, 200W	88a	Nec	—
2SD458	Si-N	S-L, 800/400V, 5A, 80W	23a	Mat	BU326(A), BU426(A), BUW11(A), ++
2SD459	Si-N-Darl	NF/S-L, 80V, 7A, 50W, B>1500, 3/9µs	17c(A)	Shi	BD647, BD899, BDW73B, BDX53B, ++
2SD46	Si-N	=2SD45: 150/75V	23a	Son	BD245D, BDX11, 2N3442, 2SD551, 2SD732, +
2SD460	Si-N-Darl	=2SD459: 100V	17j	Shi	BD649, BD901, BDW73C, BDX53C, ++
2SD461	Si-N	S-L, 250/250V, 3A, 80W, 1MHz	23a	Hit	BU606..606, BUX18(A..C), 2SD832, ++
2SD463	Si-N-Darl	NF/S-L, 80V, 7A, 80W, B=3000, <10/18µs	23a(A)	Shi	BDX63A, TIP141..142, 2SD628..629, ++
2SD464	Si-N-Darl	=2SD463: 100V	23a	Shi	BDX83B, TIP142, 2SD628..629, ++
2SD465	Si-N-Darl	S-L, 500/400V, 50A, 400W, B>150	≈74	Shi	—
2SD466	Si-N-Darl	=2SD465: 600/450V	≈74	Shi	—
2SD467	Si-N	Uni, 25V, 0,7A, 0,5W, 280MHz	7c	Hit	(BC337..338, BC635, BC637, BC639, ++)
2SD468	Si-N	=2SD467: 1A, 0,9W, 190MHz	7c(9mm)	Hit	2SC2238, 2SC4483, 2SD1207, 2SD1331, ++
2SD469	Si-N	S-L, 150V, 10A, 100W, 18MHz, 0,5/3,5µs	23a	Nec	BD245D, 2N3442, 2SD551, 2SD733, ++
2SD47	Si-N	=2SD45: 100/50V	23a	Son	BD245C, BDV95, BDX95, 2N5632..33, ++
2SD470(-B)	Si-N	TV-HA, 1600/700V, 1A, 15W	23a	Mat	BU505, 2SD948, 2SD1575
2SD471	Si-N	Uni, 30V, 1A, 1W, 130MHz	9b	Nec	BC337..338, BC635, BC637, BC639, ++
2SD472	Si-N-Darl+Di	NF/S-L, 150V, 10A, 80W, B>1000, 2/9µs	23a	Hit	BDV67D, 2SD822, 2SD1296, 2SD1299
2SD473	Si-N-Darl+Di	=2SD472: 100V, 15A, 100W	23a(A)	Hit	BDV67A, BDW83C, BDX67B, MJ4035, ++
2SD474	Si-N	Uni, 30V, 0,1A, 0,05W, >100MHz	9b	Hit	BC188, BC183, BC239, BC548, ++
2SD475(A)	Si-N	NF/S-L, 70V, 4A, 40W, 7MHz	17j	Hit	BD243B, BD537, BD539B, BD951, ++
2SD476(A)	Si-N	=2SD475(A)	17j	Hit	→2SD475(A)
2SD477	Si-N	NF/S-L, 200V, 2A, 80W	17j	Hit	BD289F, 2SC2660, 2SD810, 2SD760, 2SD1188
2SD478	Si-N	=2SD477	17j	Hit	→2SD477
2SD479	Si-N-Darl	NF/S-L, 40V, 4A, 40W, B=6000	14h	Mot	BD675, BD775, 2N6087..6089, ++
2SD48	Si-N	NF/S-L, 100V, 3A, 20W	2a	Fui	(BD241C, BD589C, BD989, 2SD712, ++)
2SD480	Si-N-Darl	=2SD479: 60V	14h	Mot	BD677, BD777, 2N6088..6089, ++
2SD481	Si-N-Darl	=2SD479: 80V	14h	Mot	BD679, BD779, 2N6089
2SD482	Si-N	Vid-L, 275V, 0,5A, 20W	14h	Mot	BD410, MJE840, 2N5650, 2SC2899, ++
2SD483	Si-N	=2SD482: 825V	14h	Mot	BD410, MJE840, 2N5656, 2SC2899, ++
2SD484	Si-N	=2SD482: 875V	14h	Mot	BD410, 2N5657, 2SC2899, 2SC6051, ++
2SD485	Si-N	NF/S-L, 40V, 4A, 40W	14h	Mot	BD185, BD487, BD785, 2N5190..92, ++
2SD486	Si-N	=2SD485: 60V	14h	Mot	BD187, BD489, BD787, 2N5191..92, ++
2SD487	Si-N	=2SD485: 80V	14h	Mot	BD189, BD441, BD787, 2N5192, ++
2SD488	Si-N	NF/S-L, 40V, 3A, 80W	14h	Mot	BD175, BD165, BD437, 2N4921..23, ++
2SD489	Si-N	=2SD488: 60V	14h	Mot	BD177, BD187, BD439, 2N4922..23, ++
2SD49	Si-N	NF/S-L, 100V, 3A, 18W	22a	Son	BD241C, BD539C, BD939, 2SD877, ++
2SD490	Si-N	=2SD488: 80V	14h	Mot	BD179, BD189, BD441, 2N4923, ++
2SD491	Si-N	NF/S-L, 70V, 10A, 90W	16h	Mot	BD207, MJE3055

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2SD492	Si-N	=2N3055	28a	Mot	→2N3055
2SD493	Si-N	NF/S-L, 60V, 5A, 75W	16h	Mot	BD199, 2N5977. 5979
2SD494	Si-N	=2SD493: 60V	16h	Mot	2N5976. 5979
2SD495	Si-N	=2SD493: 100V	16h	Mot	2N5979
2SD496	Si-N-Darl	NF/S-L, 60V, 8A, 75W, B=3000	16h	Mot	(BDV65(A..C), TIP140..142)
2SD497	Si-N-Darl	=2SD496: 60V	16h	Mot	(BDV65A..C, TIP141..142)
2SD498	Si-N-Darl	=2SD496: 100V	16h	Mot	(BDV65B..C, TIP142)
2SD499	Si-N	NF/S-L, 60V, 8A, 90W	16h	Mot	BD207, 2N5983..5985
2SD50	Si-N	NF/S-L, 100V, 8A, 50W	28a	Hit, Fui	BD245C, BDV95, BDX95, 2N5632..33, ++
2SD500	Si-N	=2SD499: 60V	16h	Mot	2N5984. 5985
2SD501	Si-N	=2SD499: 100V	16h	Mot	2N5985
2SD502	Si-N-Darl	NF/S-L, 60V, 8A, 100W, B=3000	28a	Mot	BDV65(A..C), BDX83AC, BDX85A..C, ++
2SD503	Si-N-Darl	=2SD502: 80V	28a	Mot	BDV65A..C, BDX83B..C, BDX85B..C, ++
2SD504	Si-N-Darl	NF/S-L, 60V, 12A, 150W, B=3000	28a	Mot	BDV65(A..C), BDW83A..D, BDX87A..C, ++
2SD505	Si-N-Darl	=2SD504: 60V	28a	Mot	BDV65A..C, BDW83B..D, BDX87B..C, ++
2SD506	Si-N-Darl	=2SD504: 100V	28a	Mot	BDV65B..C, BDW83C..D, BDX87C, ++
2SD507	Si-N	S-L, 90V, 250A, 625W, <5/10µs	58b	Mit	—
2SD508	Si-N	=2SD507: 110V	58b	Mit	—
2SD509	Si-N	=2SD507: 160V	58b	Mit	—
2SD51	Si-N	NF/S-L, 100V, 8A, 50W	28a	Son, Tos	BD245C, BDV95, BDX95, 2N5632..33, ++
2SD510	Si-N	=2SD507: 150V	58b	Mit	—
2SD511	Si-N	S-L, 90V, 250A, 625W, <5/10µs	58b	Mit	—
2SD512	Si-N	=2SD511: 110V	58b	Mit	—
2SD513	Si-N	=2SD511: 130V	58b	Mit	—
2SD514	Si-N	S-L, 90V, 250A, 625W, <5/10µs	58b	Mit	—
2SD515	Si-N	=2SD514: 110V	58b	Mit	—
2SD516	Si-N	NF/S-L, 20V, 1,5A, 5W, B=100..500	14h	Nec	BD135, BD165, BD228, BD233B, ++
2SD517	Si-N	TV-HA, 1500/700V, 6A, 16W(Tc=90°)	23a	Mat	BU208(A), BU508(A), 2SC3023..3024, ++
2SD518	Si-N	S-L, 220/200V, 4A, 80W, 80MHz	22a	Fui	BU406..409, 2SC2767, 2SD422..428, ++
2SD519	Si-N	S-L, 600/400V, 10A, 100W, <3,5/6,5µs	28a	Fui	BUW25..26, BUW85..86, 2SC8046, ++
2SD51A	Si-N	=2SD51: 150V	28a		BD245D, BDX11, 2N8442, 2SD551, 2SD782, ++
2SD52	Si-N	NF/S-L, 100V, 8A, 60W	28a	Fui, Sak, Tos	BD245C, BDV95, BDX95, 2N5632..33, ++
2SD520	Si-N-Darl	S-L, 600/400V, 7A, 100W, B>350	28a	Mit	BUW81(A), 2SD528, 2SD605, 2SD705, ++
2SD521	Si-N-Darl	S-L, 700/450V, 8A, 100W, B>200	28a	Mit	BUT50P, BUW81A, 2SC3030..3033
2SD522	Si-N	NF/S-L, 100V, 10A, 100W	23a	Tos	BD317, BDW21C, 2N3055, 2N5632..34, ++
2SD523	Si-N-Darl+Di	NF/S-L, 60V, 7A, 50W, B>2000	23a(A)	Tos	BDV65A, BDX83A, MJ1001, 2N6056, ++
2SD524	Si-N-Darl+Di	NF/S-L, 100V, 15A, 100W, B>2000	23a(A)	Tos	BDW83B, BDX67A, MJ4034..4035, ++
2SD525	Si-N	HiFi-NF-E, 100V, 5A, 40W, 12MHz	17j	Tos	BD243C, BD539C, BD543C, BD953, ++
2SD526	Si-N	HiFi-NF-E, 60V, 4A, 30W, >3MHz	17j	Mic, Tos	BD243B, BD537, BD539B, BD951, ++
2SD528	Si-N-Darl	S-L, 600/500V, 8A, 100W, B>350	23a	Hit	BUW81(A), 2SD520..521, 2SD605, 2SD705
2SD529	Si-N	S-L, 850/320V, 5A, 85W, 4MHz	23a	Son	BU326A, BU426A, BUS11(A), 2SC3155, ++
2SD52A	Si-N	=2SD52: 130V	23a		BD245D, BDX11, 2N3442, 2SD551, 2SD732, ++
2SD53	Si-N	NF/S-L, 90V, 10A, 100W	23a	Fui, Tos	BD245C, BDV95, BDX95, 2N5632..33, ++
2SD530	Si-N-Darl	NF/S-L, 100V, 10A, 50W, B>750	23(3pins)	Fui	—
2SD531(-1,-2)	Si-N	NF/S-L, 100V, 5A, 43W, 9MHz	17j	Son	BD243C, BD539C, BD953, 2SD613, ++
2SD532	Si-N	S-L, 200/70V, 7A, 70W, 9MHz	23a	Son	BU606..608, 2SC2262, 2SC2769, 2SD751, ++
2SD533	Si-N	S-L, 270/90V, 10A, 100W, 8MHz	23a	Son	BUX17(A..C), BUX42..43, BUY18, ++
2SD534	Si-N	NF/S-L, 110V, 12A, 100W, 5MHz	23a	Son	BD317, BDW10, 2N3055, 2N5629..31, ++
2SD535	Si-N	S-L, 250/120V, 12A, 150W, 1,5/8µs	23a	Nec	BUW74, BUX41..42, MJ15022, 2SD583, ++
2SD536	Si-N	S-L, 200/200V, 10A, 100W, -/1,8µs	23a	Fui	BUX17(A..C), BUX42..43, BUY18, ++
2SD537	Si-N	=2SD536: 200/150V	23a	Fui	BUX17(A..C), BUX42..43, BUY18, ++
2SD538(A)	Si-N	S-L, 500/400V, 10A, 100150W, 15MHz	23a	Fui	BUW25..26, BUW34..36, 2SC3046, ++
2SD539(A)	Si-N	=2SD538(A): 400/350V	23a	Fui	BUW24..26, BUW34..36, 2SC3046, ++
2SD53A	Si-N	=2SD53: 130V	23a		BD245D, BDX11, 2N3442, 2SD551, 2SD733, ++
2SD54	Si-N	NF/S-L, 100V, 10A, 150W	38a	Fui, Tos	(BD249C, BD745C, 2SD1049)
2SD540	Si-N	S-L, 200/200V, 30A, 200W, 25MHz	68a	Fui	2SC2249, 2SC2445, 2SC2940, 2SC3224, ++
2SD541	Si-N	=2SD540: 200/150V	68a	Fui	2SC2249, 2SC2445, 2SC2940, 2SC3224, ++
2SD542	Si-N	S-L, 400/400V, 30A, 200W, 20MHz	68a	Fui	2SC1302, 2SC1401, 2SC1470, 2SC2250, ++
2SD543	Si-N	=2SD542: 400/350V	68a	Fui	2SC1302, 2SC1401, 2SC1470, 2SC2250, ++
2SD544(-1,-2)	Si-N	=2SD531-..	17j	Son	→2SD531
2SD545(NP)	Si-N	Uni, Io-sat, 25V, 1A, 0,5W, 160MHz	7c(9mm)	Say, Mic	2SC4483..85, 2SD1207, 2SD1247
2SD546	Si-N	S-L, TV-VA, 800/500V, 1A, 80W, 7MHz	22a	Mat	BUV86(A), BUX84..85, 2SC1828, 2SC3352
2SD547	Si-N-Darl	S-L, 600/450V, 50A, 400W, 1/10,5µs	~74	Tos	—
2SD548	Si-N-Darl	S-L, 600/450V, 120A, 770W, 3/20µs		Tos	—
2SD549	Si-N-Darl	NF/S-L, 60V, 1,5A, 15W, B>4000	14h	Tos	BD675, BD775, 2SD985..986, 2SD1879, ++
2SD55	Si-N	NF/S-L, 100V, 20A, 200W	23a	Tos	BDW80, BDY29, MJ602, 2N6772, 2SD797++

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2SD550	Si-N	NF/S-L, 120V, 7A, 40W, 10MHz	22a	Tos	BD243C, BD548D, MJ15028, 2SD866
2SD551	Si-N	NF/S-L, 150V, 12A, 100W, 15MHz	23a	Tos	BD745E, 2SC1584, 2SD733, 2SD1047, ++
2SD552	Si-N	S-L, 220V, 15A, 150W, 4MHz, 1/4µs	23a	Tos	BUX41, 2SC1586, 2SC2608, 2SC3283, 2SD583
2SD553	Si-N	lo-sat, 70V, 7A, 40W, 10MHz, 0,2/3µs	17j	Tos	2SC8254, 2SD1287L
2SD554	Si-N	S-L, 250V, 2A, 30W	22a	Nec	BUX87(A..C), 2N3583..85, 2SD610, ++
2SD555	Si-N	S-L, NF-L, 250V, 10A, 200W, 15MHz	23a	Nec	BUX17A..C, BUY18, 2SC1576, 2SD583, ++
2SD558	Si-N	S-L, 110V, 15A, 120W, 8MHz	23a	Sak	BD745C, BDW10, 2N5630..31, 2SD1105, ++
2SD557	Si-N	=2SD556: 140V	23a	Sak	BD745E, BDW10, 2N5631, 2SC2607..08, ++
2SD558	Si-N-Darl	NF/S-L, 90V, 2A, B>2000, 0,4/3µs	80j	Nec	2SD1223, 2SD1520, 2SD1980
2SD55A	Si-N	=2SD55: 130V	23a		BDW30, BDW32, BDY58
2SD56	Si-N	S-L, 220V, 3A, 30W	22a	Son	D44Q3, TIP75(A..C), 2SC667A, 2SC2787, ++
2SD560	Si-N-Darl+Di	NF/S-L, 150V, 5A, 30W, B=2k..15k	22c(A)	Nec	2SD830, 2SD1128, 2SD1169, 2SD1590, ++
2SD565	Si-N-Darl+Di	S-L, 400/400V, 10A, 100W, B>800	23a(G)	Nec	BU920..922, MJ10002..03, 2SD685, ++
2SD568	Si-N	NF/S-L, 100V, 7A, 40W	17j	Nec	BD243C, BD543B, BD799, BD809, ++
2SD569	Si-N	NF/S-L, 100V, 7A, 40W	17j	Nec	BD243C, BD543B, BD799, BD809, ++
2SD57	Si-N	NF/S-L, 30V, 3A, 20W	22a	Mit	BD241, BD533, BD933, 2SD877, ++
2SD570	Si-N	NF/S-L, 70V, 4A, 80W, >3MHz	17j	Mat, Mic	BD243A, BD537, BD539B, BD951, ++
2SD571	Si-N	Uni, 80V, 0,7A, 1W, 110MHz	9b	Nec	BC637, BC639, BCX24, 2SD667, ++
2SD572	Si-N-Darl	S-L, 500/400V, 15A, 150W, B>80	23a	Shi	BU932, 2SD683, 2SD711(A)
2SD573	Si-N-Darl	=2SD572: 800/450V	23a	Shi	2SD663, 2SD711A
2SD574(A)	Si-N-Darl	S-L, 120/120V, 30A, 400W, B>200	68a	Shi	—
2SD575	Si-N	TV-HA, 1400/600V, 2,5A, 50W	23a	Say	BU205..206, 2SC1922, 2SD818..819, ++
2SD575L	Si-N	=2SD575: 1200/600V	23a		BU204..206, 2SC1922, 2SD818..819, ++
2SD576	Si-N	S/Vid, 250V, 0,5A, 0,8W, 200MHz	2a	Fui	BFQ38..40, 2N5010, (BF757..759, ++)
2SD577	Si-N	TV-HA, 1500V, 3A, 18W(Tc=90°)	23a	Mat	BU208..209(A), BU508(A), 2SC3023..24++
2SD578	Si-N-Darl	S-L, 500/140V, 8A, 100W, B>350	23a	Hit	BU922, 2SD528, 2SD605, 2SD796, ++
2SD578(A)	Si-N	NF/S-L, 180V, 2A, 80W	17j	Hit	BD239E, 2SC2660, 2SD760, 2SD1138, ++
2SD579(A)	Si-N	NF/S-L, 100V, 4A, 40W	22a	Hit	BD243C, BD539C, BD953, 2N3787, ++
2SD58	Si-N	=2SD57: 80V	22a	Mit	BD241A, BD535, BD935, 2SD877, ++
2SD580	Si-N	NF/S-L, 80V, 1A, 20W, 1,2MHz	2a	FUI	(BD137, BD167, BD228, BD235, ++)
2SD581(A)	Si-N	NF/S-L, 150V, 7A, 60W	23a	Hit	BDX11, 2SD732, 2SD751, 2SD1046, ++
2SD582(A)	Si-N	NF/S-L, 180V, 12A, 100W	23a	Hit	BDW14, MJ15015, 2SC2607..08, 2SD424, ++
2SD583	Si-N	NF/S-L, 250V, 15A, 150W	23a	Hit	BUX41, MJ15022, MJ15024, 2SC1588
2SD585	Si-N-Darl	NF/S-L, 110V, 7A, 80W, B>1100	23a	Mit	BDV65C, BDX68C, BDX65C, 2SD1210
2SD586(A)	Si-N	NF/S-L, 100V, 5A, 80W, 15MHz	19j	Nec	2SC2276, 2SD848(A), 2SD883(A)
2SD587(A)	Si-N	NF/S-L, 120V, 6A, 70W, 17MHz	19j	Nec	2SC2276, 2S846(A), 2SB883A
2SD588(A)	Si-N	NF/S-L, 150V, 7A, 80W	19j	Nec	—
2SD589	Si-N	TV-HA, 1500V, 5A, 50W	23a	Mat	BU208(A), BU508(A), 2SC2928, 2SD954, ++
2SD59	Si-N	NF/S-L, 100V, 8A, 50W	23a	Mit	BD245C, BDV95, BDX95, 2N5832..33, ++
2SD590	Si-N	NF/S, 100V, 2A, 1W, <150/2100ns	2a	Fui	2SD854, (BD379, BD529, 2SD1177..78, ++)
2SD591	Si-N	Uni, ra, 80V, 0,05A, 0,15W, 150MHz	7c	Mat	BC169, BC184, BC239, BC549, ++
2SD592(NC)	Si-N	Uni, 30V, 1A, 0,75W, 200MHz	7c	Mat	BC337..338, BC635, BC637, BC639, ++
2SD592A(ANC)	Si-N	=2SD592: 80V	7c		BC637, BC639, BCX24, 2SD687, ++
2SD593	Si-N	S, 500/400V, 0,3A, 0,8W, 15MHz	2a	Sak	2N5010..5015, 2SC1762
2SD594	Si-N	=2SD596: 800/700V	2a	Sak	2N5013..5015
2SD596	Si-N	SMD, NF, 30V, 0,7A, 170MHz	35a	Nec	BCW65..66
2SD597	Si-N	NF/S-L, 100V, 5A, 80W, 7MHz	23a	Mat	BD245C, BDV95, BDX95, 2SD731..732, ++
2SD598	Si-N	=2SD597: 120V, 8A, 80W, 6MHz	23a	Mat	BD245C, 2SC2681, 2SD731..732, ++
2SD599	Si-N	Uni, 25V, 1A, 0,35W, 180MHz	7c	Say	BC337..338, BC635, BC637, BC639, ++
2SD80	Si-N	=2SD58: 150V	23a	Mit	BD245D, BDX11, 2N3442, 2SD551, 2SD732, ++
2SD600	Si-N	NF/S-L, lo-sat, 100V, 1A, 8W, 130MHz	14h	Say	BD139, BD230, BD379, 2SD1684, ++
2SD800K	Si-N	=2SD600: 120V	14h		2SC2690(A), 2SD1392, 2SD1583, 2SD1684
2SD801	Si-N	SMD, Uni, 30V, 0,1A, 150MHz	35a	Mat	BC848..846, BCW31..33, BCW71..72, ++
2SD801A	Si-N	=2SD601: 80V	85a		BC848, BCV71..72, 2SC3328..3324
2SD602	Si-N	SMD, Uni, 30V, 0,5A, 200MHz	85a	Mat	BC817..818, BCW65..68, BCX19..20, ++
2SD802A	Si-N	=2SD602: 80V	85a		BCW65..66
2SD603	Si-N	Uni, 30V, 0,1A, 0,25W, 150MHz	9c	Mat	BC168, BC183, BC238, BC548, ++
2SD604	Si-N-Darl	NF/S-L, 180/180V, 5A, 100W, B>400	28a	Hit	2SD920..921, 2SD1090, 2SD1122..1123, ++
2SD805(D)	Si-N-Darl	S-L, 600/500V, 7A, 80W, B>200	28a	Sak	BUW81(A), 2SD520..521, 2SD528, 2SD705++
2SD606	Si-N-Darl	S-L, 600/500V, 15A, 100W, B>200	28a	Sak	BUT51P, 2SD573, 2SD683, 2SD711A
2SD808	Si-N	NF/S-L, 160/180V, 1,5A, 20W, 45MHz	17j	Nec	BD239D, 2SC2592, 2SD578, 2SD1138, ++
2SD606A	Si-N	=2SD608: 160/180V	17j		BD239E, 2SC2592, 2SD578, 2SD1138, ++
2SD81	Ge-N	NF/S, 30V, 0,1A, 0,12W	2a	Son	AC127, 2SD30
2SD810	Si-N	NF/S-L, 250/200V, 2A, 25W, 5MHz	17j	Nec	2SC2023, 2SD772B
2SD611	Si-N	NF/S-L, 100V, 7A, 30W	22a	Fui	BD243C, BD543C, BD801, 2N5429..30, ++
2SD611A	Si-N	=2SD611: 120V	22a		BD243C, BD543D, 2SD550, 2SD866

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2SD612	Si-N	NF/S-L, 25V, 2A, 10W, 100MHz	14h	Say	BD329, BD375, 2SD1380
2SD612K	Si-N	=2SD612: 35V	14h		BD375, 2SD794(A), 2SD1380
2SD613	Si-N	NF/S-L, 100V, 6A, 40W, 15MHz	17j	Say	BD243C, BD543C, BD801
2SD613P	Si-N	=2SD613: 50W	19j		2SD587..588, 2SD883(A), 2SD848(A)
2SD614	Si-N-Darl	NF/S, 100V, 3A, 0,8W, B=3000	2a	Sak	2SC2208, (BD681, BDW58C,D, 2SD1091,++)
2SD615	Si-N-Darl	=2SD614: 140V	2a	Sak	(2SD830, 2SD1091, 2SD1128, 2SD1169)
2SD616	Si-N	NF/S-L, 120V, 7A, 60W, 15MHz	23a	Say	BD245C, 2SC2681, 2SD731..733,++
2SD817	Si-N-Darl	NF/S-L, 120V, 6A, 100W, B=2500	23a	Sak	BDV65C, BDX63C, 2SD922
2SD619	Si-N	Uni, 80V, 1,5A, 0,5W, 100MHz	7c	Fui	MPS651, 2SC3328, (BD519, BD527,++)
2SD62	Ge-N	NF/S, 30V, 0,1A, 0,12W	2a	Son	AC127, 2SD30
2SD620	Si-N	=2SD619:	14h	Fui	BD139, BD230, BD379, 2SD1177..78,++
2SD621	Si-N	TV-HA, 2500/900V, 3A, 50W	23a	Say	2SD638
2SD622	Si-N	S-L, 450/400V, 3A, 30W, 25MHz	22a	Fui	BUY63..65, TIP75B,C, 2SC1466, 2SC2929,++
2SD624	Si-N	Vid, 200V, 0,5A, 0,8W, 50MHz	2a	Fui	2SD413, 2SD576, (BF757..759, MPS-U10++)
2SD625	Si-N	NF/S, 250V, 4A, 6,2W(Tc=25°), 60MHz	2a	Son	BUY49, (BU406..409, 2SC2767,++)
2SD626	Si-N-Darl	S-L, 600V, 6A, 80W, B>300, <1/45µs	23a	Say	BUW81, 2SD520, 2SD528, 2SD605, 2SD705++
2SD627	Si-N	TV-HA, 1500/600V, 3A, 50W	23a	Say	BU208..209(A), BU508(A), 2SC3023..24++
2SD628	Si-N-Darl+Di	NF/S-L, 100V, 10A, 80W, B>1000	23a(A)	Hit	BDV65B, BDX83C, BDX85C, 2N6059,++
2SD629	Si-N-Darl+Di	=2SD626: 100W	23a(A)	Hit	BDV65B, BDX83C, BDX85C, 2N6059,++
2SD63	Ge-N	NF/S, 25V, 0,1A, 0,12W	2a	Son	AC127, 2SD30
2SD630	Si-N	S-L, 50V, 30A, 200W, 0,8MHz	23a	Fui	BDX41, BDY29, MJ802, 2N3771
2SD631	Si-N	S-L, 80V, 40A, 200W	23a	Fui	2N6032, 2N6274..6275
2SD632	Si-N	S-L, 350/300V, 2,5A, 80W	23a	Mat	BUX16B,C, TIP51..54, 2SC1463, 2SC2624
2SD633	Si-N-Darl+Di	NF/S-L, 100V, 7A, 40W, B>2000	17c(A)	Tos	BD649, BD901, BDW73C, BDX53C,++
2SD634	Si-N-Darl+Di	=2SD633: 80V	17c(A)	Tos	BD647, BD899, BDW73B, BDX53B,++
2SD635	Si-N-Darl+Di	=2SD533: 80V	17c(A)	Tos	BD645, BD897, BDW73A, BDX53A,++
2SD638	Si-N	Uni, 30V, 0,1A, 0,4W, 150MHz	9c	Mat	BC168, BC183, BC238, BC548,++
2SD637	Si-N	=2SD638: 80V	9c	Mat	BC174, BC162, BC190, BC546,++
2SD638	Si-N	Uni, 30V, 0,5A, 0,6W, 200MHz	9c	Mat	BC337..338, BC635, BC637, BC639,++
2SD639	Si-N	=2SD638: 80V	9c	Mat	BC637, BC639, 2N3700..01, 2SC2235,++
2SD64	Ge-N	NF/S, 25V, 0,1A, 0,12W	2a	Son	AC127, 2SD30
2SD640	Si-N	S-L, 600/400V, 7A, 100W, 3MHz	23a	Tos	BU526, BU538, BU626A, 2SD1094,++
2SD641	Si-N	S-L600/400V, 15A, 150W, 4MHz	23a	Tos	BUS13(A), BUW45..46, BUX48A..C
2SD642	Si-N	S-L, 600/400V, 40A, 300W	86a	Tos	2SC1435
2SD643	Si-N-Darl	S-L, 300/200V, 30A, 300W, B>150	68a	Tos	—
2SD644	Si-N-Darl	S-L, 600/450V, 30A, 300W, B>150	68a	Tos	—
2SD846	Si-N-Darl	S-L, 600/450V, 30A, 350W, B>150	≈74	Tos	—
2SD646(A)	Si-N-Darl	S-L, 600/450V, 50A, 400W, B>150	≈74	Tos	—
2SD647(A)	Si-N-Darl	S-L, 800/600V, 100A, 770W, B>100		Tos	—
2SD646(A)	Si-N-Darl	S-L, 300/300V, 400A, 2500W, B>100		Tos	—
2SD649	Si-N	TV-HA, 1500/600V, 6A, 80W	23a	Mat, Tos	BU508(A), 2SC3025..3026, 2SD821,++
2SD65	Ge-N	NF/S, 25V, 0,1A, 0,12W	2a	Son	AC127, 2SD30
2SD850	Si-N-Darl+Di	S-L, 400/400V, 6A, 80W, B>500	23a	Hit	BU180A, BU284, BU828
2SD851	Si-N-Darl	S-L, 400/400V, 4A, 30W, B>500	22a	Hit	BU910..912, 2SD977, 2SD1072, 2SD1245,++
2SD652	Si-N-Darl	S-L, 500/500V, 6A, 80W, B=3000	23a	Hit	BU322(A), BUW81, 2SD796, 2SD980,++
26D654	Si-N	Uni, 50V, 0,5A, 0,67W, 190MHz	2a	Mit	BC140..141, BC300..302, 2N3053,++
2SD655	Si-N	Uni, 30V, 0,7A, 0,5W, 250MHz	7c	Hit	BC337..338, BC635, BC637, BC639,++
2SD656	Si-N	S-L, 200/180V, 1,5A, 30W, >2MHz	22a	Tos	BD239F, BUX67(A..C), 2SC783, 2SD1138,++
2SD657	Si-N	S-L, 200/200V, 1,5A, 50W	23a	Tos	BD239F, 2SC1195, 2SC2809, 2SD632
2SD658	Si-N	TV-HA, 1500/600V, 5A, 50W	23a	Hit	BU208(A), BU508(A), 2SC2928, 2SD820,++
2SD68	Ge-N	NF/S, 25V, 0,1A, 0,12W	2a	Son	AC127, 2SD30
2SD880	Si-N	Uni, S, 90V, 2A, 1W, 150/2100ns	2a	Fui	BCX40, BSS15, BSV94, 2N5320,++
2SD661	Si-N	Uni, ra, 35V, 0,1A, 0,4W, 200MHz	9c	Mat	BC168, BC184, BC239, BC549,++
2SD661A	Si-N	=2SD661: 55V	9c		BC414, BC550, 2SC2675, 2SC2390,++
2SD662	Si-N	Vid, 250/200V, 0,07A, 0,6W, 80MHz	9c	Mat	BF298..299, BF422A, 2SC3468,++
2SD682B	Si-N	=2SD882: 400/400V	9c		2SC2267, 2SC3469, 2SC4166, 2SD1385
2SD663	Si-N-Darl	S-L, 500/500V, 6A, 80W, B>400	23a	Fjd	BUW61, 2SD520, 2SD528, 2SD605, 2SD705++
2SD664	Si-N-Darl+Di	NF/S-L, 80V, 7A, 40W, B>2000	17c(A)	Tos	BD647, BD899, BDW73B, BDX53B,++
2SD665	Si-N	S-L, 200/200V, 15A, 150W, 15MHz	23a	Tos	BDW18, 2SC2607..2608, 2SD552, 2SD583,++
2SD666(A)	Si-N	Uni, 120V, 0,05A, 0,9A, 140MHz	7c(9mm)	Hit	2SC2632, 2SC3245(A), 2SC3248, 2SC3800
2SD667(A)	Si-N	=2SD666(A:) 1A	7c(9mm)	Hit	2SC2383, 2SC3228, 2SD1292, 2SD1812
2SD668(A)	Si-N	NF/S/Vid-L, 180V, 0,05A, 20W, 140MHz	14h	Hit	BF459, BF471, BF415, BF417, 2SC3416
2SD669(A)	Si-N	=2SD666: 1,5A	14h	Hit	2SC3117
2SD67	Si-N	S-L, 120V, 5A, 50W, 100MHz	23a	Say	2SC2706, 2SC2837, 2SC2987(A), 2SD1047
2SD670	Si-N-Darl+Di	NF/S-L, 100V, 15A, 100W, B>1000	23a	Hit	BDV67A, BDW83C, BDX67B, MJ4035,++
2SD671	Si-N	Uni, 30V, 0,5A, 0,6W, 150MHz	7c	Mat	BC337..338, BC635, BC637, BC639,++

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2SD672	Si-N	S-L, 300V, 1A, 40W(Tc=45°), 20MHz	23a	Mat	2SC1463, 2SC2809, 2SD632
2SD673(A)	Si-N	NF/S-L, 120V, 7A, 60W, 8MHz	23a	Hit	BD245C, 2SC2681, 2SD731..733, ++
2SD674(A)	Si-N	=2SD673: 80W	23a	Hit	BD245C, 2SC2681, 2SD731..733, ++
2SD675(A)	Si-N	NF/S-L, 160V, 12A, 100W, 8MHz	23a	Hit	BD745F, 2SD424, 2SD733, 2SD1047, ++
2SD676(A)	Si-N	=2SD675: 125W	23a	Hit	BD745F, 2SC2607..2608, 2SD753, ++
2SD677	Si-N	S-L, 450V, 5A, 100W	23a	Fjd	BU428(A), BUW11(A), BUW71, BUX45, ++
2SD678	Si-N-Darl	NF/S-L, 60V, 3A, 25W, B>1000	17j	Mat	BD715, BDW23A, BDW53A, 2SD837, ++
2SD678A	Si-N-Darl	=2SD678: 60V	17j		BD717, BDW23B, BDW53B, 2SD837A, ++
2SD679	Si-N-Darl	NF/S-L, 70V, 4A, 40W, B>1000	17j	Mat	BD717, BDW23B, BDW53B, BDW63B, ++
2SD679A	Si-N-Darl	=2SD679: 90V	17j		BD901, BDW23C, BDW53C, BDW63C, ++
2SD68	Si-N	=2SD67: 75V	23a	Say	2SC2681, 2SC2706, 2SC2837, (BD245B, ++)
2SD680	Si-N-Darl	NF/S-L, 90V, 8A, 60W, B>1000	23a	Mat	BDV65B, BDX63B, TIP142, 2SD1170, ++
2SD680A	Si-N-Darl	=2SD680: 110V	23a		BDV65C, BDX63C, TIP142, 2SD1170, ++
2SD681	Si-N-Darl	NF/S-L, 100V, 8A, 60W, B>1000	23a	Mat	BDV65B, BDX83B, BDX83C, TIP142, ++
2SD681A	Si-N-Darl	=2SD681: 120V	23a		BDV65C, BDW84D, BDX83C, BDX65C, ++
2SD682	Si-N-Darl	NF/S-L, 120V, 8A, 110W, B>1000	23a	Mat	BDV65C, BDV87B, BDW83D, BDX65C, ++
2SD682A	Si-N-Darl	=2SD682: 140V	23a		BDV67C
2SD683	Si-N-Darl+Di	S-L, 600/400V, 18A, 150W, B>500	23a	Tos	BUT51, 2SD573, 2SD606, 2SD711A
2SD683A	Si-N-Darl+Di	=2SD683: 600/450V	23a		BUT51, 2SD573, 2SD606, 2SD711A
2SD684	Si-N-Darl	S-L, 600/300V, 6A, 30W, B>1500	22a	Tos	BU810, 2SC3579, 2SD798..799
2SD684A	Si-N-Darl+Di	S-L, 600/400V, 6A, 30W, B>600	22a		BU810, 2SC3579, 2SD799
2SD685	Si-N-Darl+Di	S-L, 600/400V, 10A, 100W, B>400	23a	Tos	BUW81(A), MJ10013..14, 2SC3282
2SD686	Si-N-Darl+Di	NF/S-L, 100V, 4A, 30W, B>2000	17c(A)	Tos	BD901, BDW23C, BDW53C, BDW63C, ++
2SD687	Si-N-Darl+Di	NF/S-L, 60V, 3A, 25W, B>2000	17c(A)	Tos	BD899, BDW23A, BDW53A, BDW63A, ++
2SD688	Si-N-Darl	NF/S, 100V, 1,5A, 8W(Tc=25°), B>2000	2a	Tos	2SC1679, 2SD406, (BD681)
2SD689	Si-N-Darl	=2SD688: 10W	17j	Tos	BDW53C, 2SD637B
2SD69	Si-N	NF/S-L, 140V, 3A, 50W, 13MHz	23a	Son	BDX12, 2N5760, 2SC2706, 2SC2837, ++
2SD690	Si-N	NF/S-L, 70V, 7A, 40W, 10MHz	22a	Tos	BD543B, BD799, BD809, 2N6372..73, ++
2SD691	Si-N-Darl+Di	NF/S-L, 100V, 8A, 40W, B>500	17c(A)	Mat	BD649, BD901, BDW73C, BDX53C, ++
2SD692	Si-N-Darl+Di	=2SD691: 50W	23a(A)	Mat	BDV66B, BDX83B, BDX83C, BDX85C, ++
2SD693	Si-N-Darl+Di	S-L, 450/450V, 10A, 80W, B>150	23a(G)	Mat	BU922, BUW81(A), MJ10003, 2SD685, ++
2SD694	Si-N-Darl	S-L, 400/350V, 30A, 300W, B>150	68a	Tos	—
2SD695	Si-N-Darl	S-L, 400/350V, 30A, 350W, B>150	≈74	Tos	—
2SD696(A)	Si-N-Darl	S-L, 400/350V, 50A, 400W, B>150	≈74	Tos	—
2SD697(A)	Si-N-Darl	S-L, 500/450V, 100A, 770W, B>100		Tos	—
2SD698	Si-N-Darl	S-L, 200/200V, 600A, 2500W, B>150		Tos	—
2SD699	Si-N-Darl	S-L, 300/200V, 30A, 250W, B>150	68a	Tos	—
2SD70	Si-N	NF/S-L, 40V, 2A, 15W	22a	Nec	BD239, BD241, BD933, 2SC2528, ++
2SD700	Si-N-Darl	S-L, 300/200V, 200A, 770W, B>150		Tos	—
2SD702	Si-N	S-L, 400/300V, 40A, 300W	68a	Tos	2SC1435, 2SC2366, 2SD642
2SD703	Si-N-Darl	S-L, 200/150V, 30A, 300W, B>150	68a	Tos	—
2SD704	Si-N	NF/S-L, 50V, 5A, 40W, 10MHz	16j	Mit	BD245(A..C), BDV91, BDV93, BDV95, ++
2SD705	Si-N-Darl	S-L, 600V, 8A, 80W, B=300	23a	Fjd	BUW81(A), 2SD520, 2SD526, 2SD605, ++
2SD706	Si-N-Darl	S-L, 345V, 6A, 80W, B=1000	23a	Fjd	BU322(A), BUX28..29, 2SD720, ++
2SD707	Si-N-Darl	S-L, 500V, 8A, 100W, B>200	23a	Fjd	BU922, BUW81(A), MJ10013..13, ++
2SD708	Si-N-Darl	S-L 345V, 8A, 30W, B=1000	22a	Fjd	BU910..912, 2SD835, 2SD1114, 2SD1245, ++
2SD709	Si-N-Darl	S-L, 250V, 4A, 25W, B>1500	22a	Fjd	2SD616, 2SD834, 2SD1073
2SD71	Si-N	NF/S-L, 100V, 2A, 15W	22a	Nec	BD239C, BD241C, BD937, 2SC2526, ++
2SD710	Si-N-Darl	S-L, 300V, 15A, 150W, B=500	23a	Fjd	BU930..932, 2SD572..573, 2SD683, ++
2SD711	Si-N-Darl	S-L, 500/450V, 15A, 100W, B>100	23a(G)	Fjd	BU932, 2SD572..573, 2SD606, 2SD683, ++
2SD711A	Si-N-Darl	=2SD711: 600/400V, B>200	23a(G)		BUT51P, 2SD573, 2SD606, 2SD683, ++
2SD712	Si-N	NF/S-L, 100V, 4A, 30W, 8MHz	17j	Mit	BD243C, BD539C, BD953, 2SD613, ++
2SD712A	Si-N	=2SD712: 260V	17j		TIP75(A..C), 2SC2828, 2SC2929, ++
2SD713	Si-N	NF/S-L, 100V, 5A, 40W, 8MHz	17j	Mit	BD243C, BD539C, BD953, 2SD613, ++
2SD715	Si-N-Darl	NF/S-L, 110V, 7A, 80W, B>2000	77c(E)	Mit	BDV65C, BDW83D, 2SD1210
2SD716	Si-N	HiFi-NF-E, 100V, 8A, 60W, 12MHz	16j	Tos	BD245C, BDV95, 2SC2681, 2SD895..98, ++
2SD717	Si-N	lo-sat, 70V, 10A, 60W, 10MHz	18j	Tos	2SD1167, 2SD1239L
2SD718	Si-N	NF/S-L, 120V, 8A, 80W, 12MHz	18j	Tos	BD245C, 2SC2681, 2SC2706, 2SC2837, ++
2SD72	Ge-N	NF, 30V, 0,5A, 0,21W	3a	Say	AC176, AC167, 2SD352
2SD720	Si-N-Darl	S-L, 400/400V, 7A, 100W, B>400	23a	Mit	BU322(A), BUX29, 2SD707, 2SD798, ++
2SD721	Si-N-Darl	NF/S-L, 100V, 8A, 50W, B=1000	17c(A)	Sak	BD649, BD901, BDW73C, BDX53C, ++
2SD722	Si-N-Darl	=2SD721: 120V	17c(A)	Sak	BD651, BDT21, BDW73D, BDX53E, ++
2SD723	Si-N	NF/S-L, 100V, 4A, 40W	17j	Hit	BD243C, BD539C, BD953, 2SD712, ++
2SD724	Si-N	NF/S-L, 200V, 4A, 30W	17j	Hit	BD243F, 2SC2767, 2SD772A, B
2SD725	Si-N	TV-HA, 1500/600V, 8A, 50W	23a	Hit	2SC2027
2SD726	Si-N	NF/S-L, 100V, 4A, 40W, 10MHz	17j	Hit	BD243C, BD539C, BD953, 2SD712, ++

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2SD727	Si-N	NF/S-L, 130V, 5A, 60W, 7MHz	18j	Mat	BD245D, 2SD731, 2SD751, 2SD1046, ++
2SD728	Si-N	=2SD727: 150V, 6A, 70W	18j	Mat	BD245D, 2SC3263, 2SD731, 2SD751, ++
2SD728	Si-N-Darl+Di	NF/S-L, 100V, 20A, 125W, B>1000	23a(A)	Hit	BDX69B, MJ11014, 2N6284
2SD72K	Ge-N	=2SD72: 0,72W	3a		AC176K, AC187K, 2SD352
2SD73	Si-N	NF/S-L, 100V, 5A, 60W, 20MHz	23a	Nec	BD245C, BDV95, BDX95, 2N5632..33, ++
2SD730	Si-N-Darl+Di	=2SD729: 25A	23a(A)	Hit	BDX69B, MJ11014, MJ11016
2SD731	Si-N	NF/S-L, 170V, 7A, 80W, 7MHz	18j	Mat	BD245E, 2SC3263, 2SD751
2A11317SD732(K)	Si-N	NF/S-L, 150V, 8A, 80W, 15MHz	23a	Say	BD245D, 2SC2337, 2SD551, 2SD752, ++
2SD733	Si-N	NF/S-L, 160V, 12A, 100W, 15MHz	23a	Say	BD745E, MJ15015, 2SC2607..08, ++
2SD733K	Si-N	=2SD733: 160V	23a		BD757F, MJ15015, 2SC2607..08, ++
2SD734	Si-N	Uni, Io-sat, 25V, 0,7A, 0,6W, 250MHz	7c	Say	2SC4463, 2SD1207, 2SD1302, 2SD1616, ++
2SD735	Si-N	NF/S-L, 160/120V, 12A, 100W	20j	Hit	2SC2526, 2SC2565, 2SC2766(A), 2SC2921, ++
2SD736(A)	Si-N	=2SD735: 160/140V	20j	Hit	2SC2526, 2SC2565, 2SC2766(A), 2SC2821, ++
2SD737	Si-N	NF/S-L, 160V, 12A, 120W	20j	Hit	2SC2526, 2SC2565, 2SC2766(A), 2SC2821, ++
2SD736(A)	Si-N	NF/S-L, 160V, 12A, 125W	20j	Hit	2SC2526, 2SC2565, 2SC2766(A), 2SC2921, ++
2SD74	Si-N	=2SD73: 150V	23a	Nec	BD245D, BDX11, 2N3442, 2SD551, 2SD732
2SD741	Si-N	HF/NF/S-L, 40V, 5A, 15W, 200MHz	14h	Nec	MJE200, 2SC2270, 2SC2594
2SD743(A)	Si-N	NF/S-L, 100V, 4A, 40W, 17MHz	17j	Nec	BD243C, BD539C, BD953, 2SD726, ++
2SD745	Si-N	NF/S-L, 140V, 10A, 120W, 15MHz	20j	Nec	2SC2564..2565, 2SC2838, 2SD845, ++
2SD745A	Si-N	=2SD745: 150V	20j		2SC2526, 2SC2565, 2SC2838, 2SD845, ++
2SD745B	Si-N	=2SD745: 160V	20j		2SC2526, 2SC2565, 2SC2766(A), 2SC2921, ++
2SD746	Si-N	NF/S-L, 160V, 10A, 200W, 15MHz	4-SILP	Nec	—
2SD746A	Si-N	=2SD746: 220V	4-SILP		—
2SD747	Si-N	S, 50V, 0,5A, <1µs	2a	Mit	BSW61..64, BSX33, 2N2221..2222(A), ++
2SD748	Si-N	S-L, 250/200V, 3A, 80W	23a	Hit	TIP51..54, 2SC1463, 2SD832
2SD748A	Si-N	=2SD748: 250/250V	23a		TIP51..54, 2SC1463, 2SD632
2SD749	Si-N	S-L, 750/300V, 3A, 50W	23a	Mat	BUW11(A), BUX46(A), 2SC3088, 2SC3448++
2SD75	Ge-N	NF, 25V, 0,1A, 0,15W	2a	Hit	AC127, AC176, AC187, 2SD30
2SD750	Si-N	NF/S-L, 110V, 15A, 100W, 1MHz	23a	Mat	BD317, BD745C, 2N3055, 2N5629..31, ++
2SD751	Si-N	NF/S-L, 200V, 9A, 100W, 7MHz	18j	Mat	BD245F, 2SC3263
2SD752	Si-N	NF/S-L, 160V, 15A, 150W	23a	Hit	BDW12, MJ15015, 2N3773, 2SC2607..08, ++
2SD753	Si-N	=2SD752: 200V	23a	Hit	BDW16, MJ15015, 2SC1585, 2SC2607..08++
2SD754	Si-N	Uni, 25V, 0,7A, 0,625W, 280MHz	7e	Hit	(BC337..338, BC635, BC637, BC639, ++)
2SD755	Si-N	Uni, 100V, 0,05A, 0,75W, 350MHz	7c(9mm)	Hit	2SC2632, 2SC3245(A), 2SC3248, 2SD3800
2SD756	Si-N	=2SD755: 120V	7c(9mm)	Hit	2SC2632, 2SC3245(A), 2SC3248, 2SC3800
2SD756A	Si-N	=2SD755: 140V	7c(9mm)		2SC2375, 2SC2631..32, 2SC3248, 2SC3245A, ++
2SD757	Si-N	NF/S/Vid-L 160V, 0,05A, 140MHz	17j	Hit	2SC3514, (BF415, BF417, BF469, BF471, ++)
2SD756	Si-N	=2SD757: 200V	17j	Hit	2SC1819, (BF415, BF417, BF469, BF471, ++)
2SD759	Si-N	NF/S-L, 160V, 2A, 25W, 100MHz	17j	Hit	2SC2529, 2SC2660
2SD75A	Ge-N	=2SD75: 45V	2a		—
2SD760	Si-N	=2SD759: 200V	17j	Hit	2SC2860
2SD761	Si-N	NF/S-L, 160V, 1,5A, 20W	17j	Say	BD239E, 2SD608A, 2SD810, 2SD1136, ++
2SD762	Si-N	NF/S-L, 60V, 3A, 25W	17j	Mat	BD241A, BD535, BD539A, BD935, ++
2SD782A	Si-N	=2SD762: 60V, 4A, 30W	17j		BD243B, BD537, BD539B, BD951, ++
2SD763	Si-N	Uni, TV-HA, 120V, 1A, 0,9W	7c(9mm)	Hit	(2SC2383, 2SC3228, 2SD667(A), 2SD1812)
2SD764	Si-N	TV-HA, 1500/600V, 1,5A, 50W	23a	Hit	BU205..208, 2SC1922, 2SD818..819, ++
2SD765	Si-N	TV-HA, 1500/800V, 3A, 50W	23a	Hit	BU207..209(A), BU508(A), 2SC3023..24++
2SD766	Si-N	S-L, NF-E, 300V, 0,7A, 30W, 45MHz	22a	Mat	BUW40(A,B), TIP47..50, 2SC782, ++
2SD767	Si-N	Uni, 60V, 0,1A, 0,25W, 150MHz	7c	Mat	BC174, BC162, BC190, BC546, ++
2SD768(K)	Si-N-Darl+Di	NF/S-L, 120V, 6A, 40W, B>1000	17c(A)	Hit	BD651, BDW63D, BDW73D, BDT21
2SD769	Si-N	Uni, 20V, 0,5A, 0,4W	7c	Mat	BC337..338, BC635, BC637, BC839, ++
2SD77	Ge-N	NF, 25V, 0,1A, 0,15W	2a	Hit	AC127, AC176, AC187, 2SD30
2SD770	Si-N	=2SD769: 50V	7c	Mat	BC337, BC635, BC637, BC639, ++
2SD771	Si-N	Uni, 25V, 0,05A, 0,15W	7c	Mat	BC168, BC183, BC238, BC548, ++
2SD772	Si-N	NF/S-L, 150V, 5A, 40W, 40MHz	17j	Mat	MJE15030
2SD772A	Si-N	=2SD772: 200V	17j		—
2SD772B	Si-N	=2SD772: 250V	17j		—
2SD773	Si-N	NF, Io-sat, 20V, 2A, 1W, 110MHz	9b	Nec	2SC3225, 2SC4484, 2SD1248..47
2SD774	Si-N	Uni, 100V, 1A, 1W, 95MHz	9b	Nec	2SD1616A, 2SD1768, 2SD1857, (BC639)
2SD776	Si-N	S-L, hi-beta, 200V, 5A, 100W, B>500	23a	Tos	2SD1090
2SD777	Si-N	TV-Reg, hi-beta, 65V, 4A, 100W, B>500	23a	Tos	—
2SD778	Si-N	Uni, 30V, 0,1A, 0,4W	9c	Mat	BC168, BC163, BC236, BC548, ++
2SD779	Si-N	=2SD778: 60V	9c	Mat	BC174, BC182, BC190, BC548, ++
2SD77A	Ge-N	=2SD77: 45V	2a		—
2SD78(A)	Si-N	NF/S, 100V, 2A, 1W	2a	Nec	BCX40, BSS15, 2N5320, (BD529, ++)
2SD760	Si-N	SMD, Uni, 60V, 0,3A, 140MHz	35a	Nec	BCW65..66

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2SD780A	Si-N	=2SD780: 80V	35a		BCW66
2SD781	Si-N	S-L, TV-HA, 150V, 2A	14h	Hit	2SD975
2SD782	Si-N	HV, 700/400V, 5A, 30W	17c	Hit	BU406..406, 2SD884..885, 2SD1150,++
2SD783	Si-N	HV, 700/400V, 4A, 50W	17c	Hit	BU208..209(A), BU508(A), 2SC2928, ++
2SD784	Si-N	=2SD783: 1700/700V, 5A	23a	Hit	BU209(A), 2SC3026
2SD785	Si-N	=2SD783: 1900/700V, 5A	23a	Hit	2SC2125
2SD786(S)	Si-N	NF, ra, 50V, 0,3A, 0,25W, 100MHz	7c,41c	Rhm	BC184, BC413..414, BC550, 2SC2390, ++
2SD787	Si-N	NF-E, 20/16V, 2A, 0,9W, 100MHz	7c(9mm)	Hit	2SD1100, 2SD1014, 2SD1146, 2SD1207, ++
2SD788	Si-N	=2SD787: 20/20V	7c(9mm)	Hit	2SD1100, 2SD1014, 2SD1146, 2SD1207, ++
2SD789	Si-N	NF/E, 100/50V, 1A, 0,9W, 100MHz	7c(9mm)	Hit	2SC2383, 2SC3228, 2SD667(A), 2SD1812, ++
2SD79	Si-N	=2SD78:	43a	Nec	(BD237, BD239C, BD529, BD817,++)
2SD790	Si-N	=2SD789: 100/70V	7c(9mm)	Hit	2SC2383, 2SC3228, 2SD667(A), 2SD1812, ++
2SD792	Si-N	TV-HA, 1500/700V, 5A, 35W(Tc=90°)	23a	Mat	BU208(A), BU508(A), 2SC2928, 2SD954,++
2SD793	Si-N	NF/S-L, 40V, 3A, 10W, 65MHz	14h	Nec	BD785, MJE240..244, 2SD1348
2SD794(A)	Si-N	NF/S-L, 70V, 3A, 10W, 80MHz	14h	Nec	BD787, BD789, MJE240..244
2SD795(A)	Si-N	NF/HF-L, 50V, 3A, 20W, 95MHz	17j	Nec	2SC3252
2SD798	Si-N-Darl	S-L, 500V, 8A, 100W, B>200, <1,4/21µs	23a	Fjd	BU922, BUW81(A), 2SD707, 2SD885, ++
2SD797	Si-N	S-L, 100V, 30A, 200W, 3MHz, 1,5/7µs	23a	Tos	BDW30, BDY29, MJ802
2SD798	Si-N-Darl	S-L, 600/300V, 6A, 30W, B>1500	17j	Tos	BU810, 2SC3579
2SD799	Si-N-Darl+Di	S-L, 600/400V, 6A, 30W, B>600	17c(A)	Tos	BU810, 2SC3579
2SD80	Si-N	NF/S-L, 30V, 6A, 50W, 1320/4500ns	23a	Sak	BD245, BDV91, BDX91, 2N5873..74,++
2SD800	Si-N	S-L, 750V, 4A, 30W, 8MHz	23a	Hit	BU311(A), BUW11(A), BUX82..83, ++
2SD801	Si-N	S-L, TV-SN, 600/375V, 8A, 50W	23a	Hit	BU326(A), BU426(A), BU526, 2SD1093
2SD802	Si-N	=2SD801: 900/400V	23a	Hit	BU326A, BU426A, BU526, 2SD1093
2SD803	Si-N-Darl+Di	NF/S-L, 120V, 8A, 100W, B>2000	23a(A)	Mat	BDV65C, BDX63C, 2SD922, 2SD1210
2SD804	Si-N	NF/S-L, 60V, 3A, 25W	17j	Mat	BD241A, BD535, BD539A, BD935, ++
2SD805	Si-N-Darl	S-L, 600/600V, 30A, 200W, B>100	68a	Fjd	—
2SD806	Si-N-Darl	=2SD805: 50A, 400W	23a	Fjd	—
2SD807	Si-N	TV-HA, 1500/800V, 5A, 50W	28a	Sak	BU208(A), BU508(A), 2SC2928, 2SD954,++
2SD806	Si-N	Uni, 25V, 0.5A, 0,4W, 250MHz	7c	Hit	BC337..338, BC635, BC637, BC639, ++
2SD809(1)	Si-N	NF/S-L, lo-sat, 100V, 1A, 10W, 85MHz	14h	Nec	BD139, BD230, BD379, 2SD1177..78,++
2SD81	Si-N	=2SD80: 80V	23a	Sak	BD245A, BDV91, BDX91, 2N5873..74, ++
2SD810	Si-N	hi-beta, 20/20/20V, 4A, 30W, B=400	17j	Sak	—
2SD811	Si-N	S-L, 900/400V, 8A, 50W, 5MHz	23a	Tos	BU526, BU536, BUW12A, BUX47A, ++
2SD812	Si-N	NF/S-L, 80V, 5A, 40W, 15MHz	17j	Mat	BD243B, BD539B, BD543B, BD951, ++
2SD813	Si-N	SMD, lo-sat, 25V, 0,5A, 150MHz	35a	Mat	2SC3265, (BC817..818, BCX19..20)
2SD814	Si-N	SMD, ra, 150/150V, 0,05A, 150MHz	35a	Mat	—
2SD814A	Si-N	=2SD814: 185/185V	35a		—
2SD815	Si-N-Darl	S-L, 120V, 30A, 300W, B=300, <3/11µs	68a	Fjd	—
2SD816	Si-N-Darl	S-L, 300V, 4A, 30W, B=1500, <2/20µs	17j	Fjd	2SD1073
2SD817	Si-N	TV-HA, 1500/600V, 1,5A, 50W	23a	Tos	BU205..206, 2SC1922, 2SC3023..24,++
2SD818	Si-N	TV-HA, 1500/600V, 2,5A, 50W	23a	Tos,Tho	BU205..206, 2SC1922, 2SD849..850,++
2SD819	Si-N	=2SD818: 3,5A	23a	Tos,Tho	BU206..209(A), BU508(A), 2SC3023..24++
2SD82	Si-N	=2SD80: 100V	23a	Sak	BD245C, BDV93, BDX93, 2N5832..33, ++
2SD820	Si-N	=2SD818: 5A	23a	Tos	BU208(A), BU508(A), 2SC2928, 2SD954,++
2SD821	Si-N	=2SD818: 6A	23a	Tos	BU508(A), 2SC3025..3026, 2SD849,++
2SD822	Si-N	=2SD818: 7A	23a	Tos	BU508(A), 2SC3027..3028, 2SD1016
2SD823	Si-N	NF/S-L, TV-HA, 200/90V, 6A, 40W	17j	Say	BU406..409, 2SD884..885, 2SD1150,++
2SD824(A)	Si-N	NF/S-L, 120V, 6A, 60W, 10MHz	20j	Hit	2SC2525..26, 2SC2564..65, 2SD745(A,B),++
2SD825(A)	Si-N	NF/S-L, 120V, 7A, 80W, 10MHz	20j	Hit	2SC2525..26, 2SC2584..65, 2SD745(A,B),++
2SD826	Si-N	lo-sat, 60V, 5A, 10W, 120MHz	14h	Say	BDX35..37
2SD827	Si-N-Darl+Di	S-L, 500/500V, 4A, 50W, B>500	20j	Hit	(2SD932)
2SD828	Si-N-Darl+Di	=2SD827: B=2000	20j	Hit	(2SD932)
2SD829(K)	Si-N-Darl+Di	NF/S-L, 150/120V, 15A, 100W, B=4000	20j	Hit	(2SD852)
2SD83	Si-N	=2SD80: 150V	23a	Sak	BD245D, BDX11, 2N3442, 2SD551, 2SD732,++
2SD830	Si-N-Darl	NF/S-L, 150/100V, 5A, 30W, B>2000	17j	Fui	BDX53F, 2SD1128, 2SD1169, 2SD1590
2SD831	Si-N-Darl	S-L, 500/400V, 20A, 150W, B=500	23a(G)	Fui	BUT13, MJ10001, MJ10005, MJ10008..09
2SD832	Si-N-Darl	S-L, 600/400V, 50A, 400W, B=200	23a	Fui	—
2SD833	Si-N-Darl	NF/S-L, 60V, 7A, 40W, B>4000	23a(G)	Fjd	(BD645, BD897, BDW73A, BDX53A,++)
2SD834	Si-N-Darl	S-L, 250/200V, 4A, 25W, B>1500	17j	Fjd	2SD816, 2SD1073
2SD835	Si-N-Darl	S-L, 400/400V, 6A, 40W, B>400	17j	Fjd	BU910..912, 2SD1114, 2SD1245
2SD836	Si-N-Darl+Di	NF/S-L, 60V, 2A, 35W, B>1000	17c(A)	Mat	BD715, BDW23A, BDW53A, BDW63A, ++
2SD836A	Si-N-Darl+Di	=2SD836: 80V	17c(A)		BD717, BDW23B, BDW53B, BDW63B, ++
2SD836B	Si-N-Darl+Di	=2SD836: 100V	17c(A)		BDW23C, BDW53C, BDW63C, ++
2SD837	Si-N-Darl+Di	NF/S-L, 60V, 4A, 40W, B>1000	17c(A)	Mat	BD645, BD897, BDW23A, BDW63A, ++
2SD837A	Si-N-Darl+Di	=2SD837: 80V	17c(A)		BD647, BD899, BDW23B, BDW83B, ++

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2SD837B	Si-N-Darl+Di	=2SD837: 100V	17c(A)		BD649, BD901, BDW23C, BDW63C, ++
2SD838	Si-N	TV-HA, 2500/900V, 3A, 50W	23a	Say	2SD621
2SD839	Si-N-Darl	NF/S-L, 35V, 4A, 30W, B>1000	17j	Mit	BD713, BDW23, BDW53, BDW83, ++
2SD84	Si-N	=2SD60: 200V	23a	Sak	BD245F, BD550A,B, 2SC2262, 2SD751
2SD840	Si-N-Darl	NF/S-L, 70V, 5A, 40W, B>1000	17j	Mit	BD847, BD899, BDW23B, BDW63B, ++
2SD841	Si-N	S-L, TV-SN, 800/400V, 3A, 40W, 4MHz	17j	Tos	BUT11(A), BUV48(A), 2SC3047, 2SC3086++
2SD842	Si-N-Darl+Di	NF/S-L, 80V, 30A, 150W, B=4000	23a(A)	Tos	BDXF1146569A..C, MJ11014, 2SD1460, ++
2SD843	Si-N	Io-sat, 100V, 7A, 40W, 10MHz	17j	Tos	(2SD1237L)
2SD844	Si-N	NF/S-L, Io-sat, 50V, 7A, 60W, 15MHz	18j	Tos	2SD1063
2SD845	Si-N	NF/S-L, 150V, 12A, 120W, 20MHz	20j	Tos	2SC2526, 2SC2766(A), 2SC2838, 2SC2921, ++
2SD846	Si-N	NF/S-L, 200V, 15A, 150W, 20MHz	20j	Tos	2SC2773..2774, 2SC3264, 2SC3370
2SD847	Si-N	NF/S-L, S-Reg, 40V, 15A, 80W	18j	Fjd	BD249, BD545, BD745, 2SC3256
2SD848	Si-N	NF/S-L, 120V, 7A, 80W	18j	Nec	2SC2276, 2SD588
2SD648A	Si-N	=2SD848: 130V	19j		2SC2276, 2SD588
2SD849	Si-N	TV-HA, 1500/600V, 3A, 70W	23a	Mat	BU208..209(A), BU508(A), 2SD850, ++
2SD850	Si-N	TV-HA, 1500/700V, 3A, 65W	23a	Mat	BU208..209(A), BU508(A), 2SD649, ++
2SD851	Si-N-Darl+Di	S-L, 150V, 10A, 80W, B=3000, 1/7µs	20j	Nec	2SD829
2SD852	Si-N-Darl+Di	S-L, 150V, 15A, 100W, B=3000	20j	Nec	2SD829
2SD854	Si-N	S, 100V, 2,2A, 10W(Tc=25°), <100/500ns	2s	Mit	—
2SD855	Si-N	NF/S-L, 60V, 1A, 30W, -/1µs	17j	Mat	BD239A, BD241A, 2SC1398, 2SC3252, ++
2SD855A	Si-N	=2SD855: 60V	17j		BD239B, BD241B, 2SC2275(A), 2SC3252, ++
2SD855B	Si-N	=2SD855: 100V	17j		BD239C, BD241C, 2SC2275(A), 2SC2528, ++
2SD856	Si-N	NF/S-L, 60V, 3A, 35W, -/3µs	17j	Mat	BD241A, BD535, BD539A, BD935, ++
2SD856A	Si-N	=2SD856: 60V	17j		BD241B, BD537, BD539B, BD937, ++
2SD858B	Si-N	=2SD856: 100V	17j		BD241C, BD539C, BD937, 2SD613, ++
2SD857	Si-N	NF/S-L, 60V, 4A, 40W, -/1,4µs	17j	Mat	BD243A, BD535, BD539A, BD949, ++
2SD857A	Si-N	=2SD857: 60V	17j		BD243B, BD537, BD539B, BD951, ++
2SD857B	Si-N	=2SD857: 100V	17j		BD243C, BD539C, BD953, 2SD613, ++
2SD856	Si-N	NF/S-L, 60V, 5A, 60W, -/1,4µs	18j	Mat	BD245A, BDV91, 2SD895, 2SD718, ++
2SD858A	Si-N	=2SD858: 60V	18j		BD245B, BDV93, 2SD895, 2SD718, ++
2SD858B	Si-N	=2SD856: 100V	18j		BD245C, BDV95, 2SD895, 2SD718, ++
2SD859	Si-N	NF/S-L, 350/250V, 0,75A, 35W, -/2µs	17j	Mat	BUW40(A,B), BUX85, TIP47..50
2SD859A	Si-N	=2SD859: 400/300V	17j		BUW40(A,B), BUX85, TIP48..50
2SD859B	Si-N	=2SD859: 450/350V	17j		BUW40(A,B), BUX85, TIP49..50
2SD860	Si-N	NF/S-L, 350/250V, 1A, 40W, -/2µs	17j	Mat	BUW40(A,B), BUX85, TIP47..50
28D860A	Si-N	=2SD860: 400/300V	17j		BUW40(A,B), BUX85, TIP48..50
2SD880B	Si-N	=2SD860: 450/350V	17j		BUW40(A,B), BUX85, TIP49..50
2SD881	Si-N	NF/S-L, 350/250V, 1,5A, 45W	17j	Mat	BUW40(A,B), BUX85, TIP47..50
2SD881A	Si-N	=2SD881: 400/300V	17j		BUW40(A,B), BUX85, TIP48..50
2SD861B	Si-N	=2SD881: 450/350V	17j		BUW40(A,B), BUX85, TIP49..50
2SD862	Si-N	NF/S-L, 20V, 2A, 10W	14h	Mat	BD175, BD233, BD329, BD375, ++
2SD863	Si-N	Uni, 80V, 1A, 0,9W, 150MHz	7c(9mm)	Say	2SD1014, 2SD1148, 2SD1207, 2SD1292, ++
2SD884(K)	Si-N-Darl+Di	NF/S-L, 120V, 3A, 30W, B>1000	17c(A)	Hit	BDW53D, BDW63D, 2SD1147
2SD865	Si-N-Darl	S-L, 300/300V, 4A, 40W, B=1500, <2/20µs	22a	Fjd	2SD818, 2SD977, 2SD1073
2SD888	Si-N	NF/S-L, Io-sat, 130V, 7A, 40W, 30MHz	17j	Mat	—
2SD868A	Si-N	=2SD866: 150V	17j		—
2SD887	Si-N	S-L, 130V, 10A, 100W, 3MHz, 1,5/5,7µs	23a	Tos	BD245D, 2N3442, 2N4348, 2SD551, ++
2SD888	Si-N+Di+Rbe=27	TV-HA, 1500/600V, 2,5A, 50W	23a	Tos	BU208D, 2SD1301, 2SD1171..1175, ++
2SD889	Si-N+Di	=2SD866: 3,5A	23a	Tos	BU208D, 2SD1171..1175, ++
2SD870	Si-N+Di	=2SD888: 5A	23a	Tos	BU208D, 2SD1171..1175, ++
2SD871	Si-N+Di	=2SD868: 6A	23a	Tos	BU508D
2SD872	Si-N	S-L, 500/400V, 5A, 40W, -/3µs	17j	Mit	BUT54, BUT56(A), 2SC2827, 2SC3497, ++
28D873	Si-N	=2N3773	23a	Tos	→2N3773
2SD874	Si-N	SMD, Uni, 30V, 1A, 200MHz	39b	Mat	BC868, BCX56, 2SC2883, 2SC2982
2SD874A	Si-N	=2SD874: 80V	39b		BCX55..56, 2SC3444, 2SD1005, 28D1418
2SD875	Si-N	SMD, Uni, 60V, 0,5A, 120MHz	39b	Mat	2SC3438, 2SD968(A), 2SD1006..1007
2SD876	Si-N	hi-beta, 200/150V, 1A, 40W, B>500	17j	Mat	2SC2317
2SD877	Si-N	NF/S-L, 110V, 3A, 25W, 3MHz, 1,5/7µs	22a	Tos	BD241C, BD939, BDW25, BDX25, ++
2SD878	Si-N	=2N3055	23a	Tos	→2N3055
2SD879	Si-N	Io-sat, 30V, 3A, 0,75W, 200MHz	7c	Say	2SD1347
2SD88(-1..-3)	Si-N	S-L, 100..300V, 5A, 80W	23a	Son	BU104, BU608..608, BUX18(A..C), ++
2SD880	Si-N	NF/S-L, 60V, 3A, 30W, 3MHz	17j	Tos	BD241A, BD537, BD937, 2SD712, ++
2SD882	Si-N	NF/S-L, Io-sat, 40V, 3A, 10W, 90MHz	14h	Nec	BD785, MJE240..244, 2SD794(A)
2SD883	Si-N	NF/S-L, 100V, 6A, 70W	19j	Nec	2SC2278, 2SD587..568, 2SD848(A)
2SD883A	Si-N	=2SD883: 120V	19j		2SC2276, 2SD587..588, 2SD848(A)
2SD864	Si-N	HV, 700/400V, 7A, 40W, -/<3µs	17c	Mat	BU406..408, 2SC3173, 2SC3590..91, ++

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2SD885	Si-N	=2SD884: 330/330V	17j	Mat	BU406..406, 2SC3173, 2SC3590..91,++
2SD886	Si-N	NF-L, hi-beta, 80/60V, 3A, 40W, B>500	17j	Mat	2SD887..888, 2SD1157, 2SD1943, 2SC1983
2SD886A	Si-N	=2SD886: 100/80V	17j		2SC2318, 2SC2491
2SD887	Si-N	NF-L, hi-beta, 80V, 4A, 40W, B>500	17j	Mat	2SC2315..16, 2SC2491, 2SD1157
2SD888	Si-N	NF-L, hi-beta, 80V, 6A, 50W, B>500	17j	Mat	2SC2315..16, 2SC2491, 2SD1158
2SD889	Si-N	hi-Ueb, 30V, 0,1A, 150MHz	7c	Mat	2SC3114, 2SC3135, 2SD1208, 2SD1807
2SD88A	Si-N	=2SD88: 10A, 120W	23a		BU109, BUX17A..C, BUY18, BUX43, ++
2SD890	Si-N	hi-Ueb, 100V, 0,02A, 0,25W, 150MHz	7c	Mat	2SC3071, 2SC3495, 2SD1011
2SD891	Si-N-Darl	Uni, 40V, 0,3A, 0,25W, B>2000	5c(A)	Mat	BC517, BC617, BC875, MPS-A13..14,++
2SD891A	Si-N-Darl	=2SD891: 80V	5a		BC875, BSR50..52, MPS-A27..29,++
2SD892	Si-N-Darl	Uni, 30V, 0,5A, 0,4W, 150MHz, B>2000	5a	Mat	BC617, BC875, BSR50..52, MPS-A27..29,++
2SD892A	Si-N-Darl	=2SD892: 80V	5a		BC875, BSR50..52, MPS-A27..29,++
2SD893	Si-N-Darl	Uni, 30V, 1A, 0,75W, 150MHz, B>2000	7a	Mat	BC617, BC875, BSR50..52, MPS-A27..29,++
2SD893A	Si-N-Darl	=2SD893: 80V	7a		BC875, BSR50..52, MPS-A27..29,++
2SD894	Si-N-Darl	NF/S-L, 30V, 1,5A, 10W, 120MHz	14b(H)	Say	2SD985..988, 2SD1379
2SD895	Si-N	NF/S-L, 100V, 6A, 80W, 15MHz	18j	Say	BD245C, BDV95, 2SC2681, 2SD718, ++
2SD896	Si-N	NF/S-L, 120V, 7A, 70W, 15MHz	18j	Say	BD245C, 2SC2681, SC2837, 2SD718, ++
2SD897(A)	Si-N+Di+Rbe=27	TV-HA, 1500V, 1,5A, 50W	23a	Hit	BU208D, 2SD1171..1175, 2SD1301
2SD898(A,B)	Si-N+Di	=2SD897: 3..3,5A	23a	Hit	BU208D, BU508D, 2SD1171..1175
2SD899(A)	Si-N+Di	=2SD897: 4..5A	23a	Hit	BU208D, BU508D, 2SD1171..1175
2SD90	Si-N	NF/S-L, 30V, 3A, 20W, -/3,8µs	22a	Sak	BD241, BD533, BD933, 2SD877,++
2SD900(A,B)	Si-N+Di	=2SD897: 5..6A	23a	Hit	BU208D, BU508D, 2SD1171..1175
2SD901	Si-N	NF/S-L, 200V, 2A, 25W	17j	Nec	BD239F, 2SC2660, 2SD780, 2SD1138, ++
2SD902	Si-N	S-L, 350V, 4A, 80W	23a	Say	BU326(A), BU426(A), BUW11(A), ++
2SD903	Si-N+Di	CTV-HA, 1500/600V, 7A, 50W	23a	Fui,Say	BU508D, 2SD994, 2SC3682, 2SD1732, ++
2SD904	Si-N+Di	CTV-HA, 1500/600V, 7A, 50W	23a	Fui,Say	BU508D, 2SD994, 2SC3682, 2SD1732, ++
2SD905	Si-N	TV-HA, 1400/650V, 6A, 50W	23a	Hit	BU508(A), 2SC3027..3028, 2SD1279
2SD906	Si-N	TV-HA, 1400/650V, 8A, 50W	23a	Hit	BU508(A), 2SC3027..3028, 2SD1279
2SD907	Si-N	NF/S-L, 80V, 10A, 80W, <1/3µs	18j	Fjd	BD245B, BD545B, BDV93, 2SC3256, ++
2SD908	Si-N	=2SD907: 120V	18j	Fjd	BD245C, BD545D, 2SC2681, 2SD1047, ++
2SD909	Si-N	NF/S-L, 80V, 15A, 80W	18j	Fjd	BD249B, BD545B, BD745B
2SD91	Si-N	=2SD90: 80V	22a	Sak	BD241A, BD535, BD935, 2SD877, ++
2SD910	Si-N	=2SD909: 120V	18j	Fjd	BD249C, BD545D, BD745D
2SD911	Si-N	NF/S-L, 80V, 15A, 100W	23a	Fjd	BD249B, BD317, BD545B, BD745B,++
2SD912	Si-N	=2SD911: 120V	23a	Fjd	BD249C, BD545D, BD745D, 2N5630..31,++
2SD913	Si-N	S-L, 200/80V, 25A, 150W, <1/2,9µs	23a	Fjd	BDW36, BUV11..12, BUX11..12,++
2SD914	Si-N	=2SD913: 200/120V	23a	Fjd	BDW36, BUV11..12, BUX11..12,++
2SD915	Si-N-Darl	S-L, 600/600V, 30A, 200W, B=300	23a	Fjd	—
2SD916	Si-N-Darl	S-L, S-Reg, 80V, 7A, 30W, B>800	17j	Fjd	BD845, BD897, BDW73A, BDX53A,++
2SD917	Si-N	Sw, 500/400V, 7A, 70W	16c	Mat	(BU425(A), BU926)
2SD918	Si-N	NF/S-L, 250V, 2A, 80W	19j	Nec	—
2SD919	Si-N	Uni, 30V, 0,5A, 0,4W, 200MHz	40c	Mat	BC337..338, BC635, BC637, BC639, ++
2SD92	Si-N	=2SD90: 100V	22a	Sak	BD241C, BD937, 2SD712, 2SD877, ++
2SD920	Si-N-Darl	NF/S-L, 200V, 5A, 100W, B>700	23a	Fjd	2SD929, 2SD931, 2SD1090, 2SD1122..23
2SD921	Si-N-Darl	=2SD920: 80W	18j	Fjd	2SD1090, 2SD1122..23
2SD922	Si-N-Darl	NF/S-L, 150V, 10A, 100W, B>700	23a	Fjd	2SD1123, 2SD1210
2SD923	Si-N-Darl	=2SD922: 80W	18j	Fjd	2SD1123, 2SD1210
2SD926	Si-N	NF/S-L, 50V, 4A, 30W	17j	Hit	BD243, BD535, BD539A, BD949, ++
2SD927	Si-N	=2SD928: 80V	17j	Hit	BD243A, BD535, BD539A, BD949, ++
2SD928	Si-N	=2SD928: 80V	17j	Hit	BD243B, BD537, BD539B, BD951,++
2SD929	Si-N-Darl	NF/S-L, 200/180V, 5A, 80W, B>700	23a	Fjd	2SD778, 2SD920..921, 2SD931, 2SD1123
2SD93	Si-N	=2SD90: 150V	22a	Sak	BD241D, 2SD772(A,B)
2SD930	Si-N-Darl	NF/S-L, 200/180V, 5A, 30W, B=5000	17j	Fjd	2SD1023, 2SD1025
2SD931	Si-N-Darl	NF/S-L, 200/180V, 5A, 50W, B>700	23a	Fjd	2SD776, 2SD920..921, 2SD929, 2SD1123
2SD932	Si-N-Darl	S-L, 500/300V, 6A, 80W, B=1500	20j	Hit	—
2SD933(H)	Si-N-Darl+Di	int Z-Diode, 300/300V, 6A, 80W, B=1500	23a	Hit	(2SD850, 2SD706, 2SD1043, 2SD1481)
2SD934(K)	Si-N-Darl+Di	S-L, 300/300V, 8A, 80W, B=1500	20j	Hit	2SD932
2SD935	Si-N	S-L, 250V, 5A, 80W	18j	Mat	TIP55A..58A, 2SC2305, 2SC2624, 2SD1150
2SD936	Si-N-Darl	S-L, 300/250V, 30A, 400W, B>150	=74	Tos	—
2SD937	Si-N-Darl	=2SD936: 400/350V	=74	Tos	—
2SD939	Si-N-Darl	=2SD936: 600/450V	=74	Tos+	—
2SD939	Si-N-Darl	S-L, 300/250V, 40A, 400W, B>150	=74	Tos	—
2SD94	Si-N	=2SD90: 200V	22a	Sak	BD241F, 2SD772A,B
2SD940	Si-N-Darl	=2SD939: 400/350V	=74	Tos	—
2SD941	Si-N-Darl	=2SD939: 600/450V	=74	Tos	—
2SD942	Si-N-Darl	S-L, 300/250V, 50A, 400W, B>150	=74	Tos	—

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2SD943	Si-N-Darl	=2SD942: 400/350V	=74	Tos	—
2SD944	Si-N-Darl	NF/S-L, 40V, 2A, 5W, 150MHz, B>4000	14b	Rhm	2SD1379
2SD946	Si-N-Darl	NF/S-L, 70V, 1A, 150MHz, B>4000	14b(A)	Mat	BD477A, B, BD875, BDX42, 2SD1379, ++
2SD946A	Si-N-Darl	=2SD946: 80V	14b(A)		BD875, BDX42..44, 2SD1376, ++
2SD946B	Si-N-Darl	=2SD946: 100V	14b(A)		BD879, BDX44, 2SD1376, 2SD1953
2SD947(F)	Si-N-Darl	NF/S-L, 40V, 1A, 5W, 150MHz, B>4000	14b	Rhm	2SD1509, (2SD1379)
2SD948	Si-N	TV-HA, 1600V, 1A, 25W	22a	Mat	BU505, 2SD470, 2SD1575
2SD949	Si-N	TV-HA, 1500V, 2A, 40W	23a	Mat	BU205..206, 2SC1922, 2SD627, 2SD618, ++
2SD950	Si-N+Di+Rbe=27	TV-HA, 1500V, 3A, 42W	23a	Mat	BU208D, 2SC3480, 2SD993, 2SD1171..75, ++
2SD951	Si-N+Di+Rbe=27	TV-HA, 1500V, 3A, 65W	23a	Mat	BU208D, 2SC3480, 2SD993, 2SD1171..75, ++
2SD952	Si-N+Di+Rbe=27	TV-HA, 1500V, 3A, 70W	23a	Mat	BU508D, 2SC3480, 2SD1173..75
2SD953	Si-N+Di+Rbe=27	TV-HA, 1500V, 5A, 95W	23a	Mat	BU508D, 2SD1174..75
2SD954	Si-N+Di+Rbe=27	TV-HA, 1500V, 5A, 95W	23a	Mat	BU508(A)
2SD955	Si-N	NF, 120V, 0,05A, 0,625W	7e	Hit	2SC1890A, 2SC2240, 2SC2363, 2SC3245(A)++
2SD956	Si-N+Di+Rbe=27	TV-HA, 1500V, 2,5A, 50W	23a	Hit	BU208D, 2SC3479, 2SD993, 2SD1171..75, ++
2SD957	Si-N+Di+Rbe=27	TV-HA, 1500V, 6A, 50W	23a	Hit	(2SD903..904, 2SD994)
2SD957A	Si-N+Di	=2SD957: 7A	23a		(2SD903..904, 2SD994)
2SD958	Si-N	NF, ra, 120V, 0,02A, 0,4W, 200MHz	9c	Mat	2SC1775A, 2SC2240, 2SC2389, 2SC2459, ++
2SD959	Si-N	NF/S-L, Io-sat, 130V, 3A, 30W, 30MHz	17j	Mat	—
2SD96	Ge-N	NF-Tr/E, 25V, 0,25A, 0,3W	2a	Hit	AC127, AC176, AC187, 2SD30, 2SD72
2SD960	Si-N	=2SD959: 4A, 35W	17j	Mat	—
2SD961	Si-N	=2SD959: 5A, 40W	17j	Mat	—
2SD962	Si-N-Darl	NF/S-L, 200V, 5A, 80W, B=3000	23a	Sak	2SD776, 2SD920..921, 2SD929, 2SD931, ++
2SD963	Si-N-Darl	=2SD962: 100W	23a		2SD776, 2SD920..921, 2SD929, 2SD931, ++
2SD965	Si-N	NF, 40V, 5A, 0,75W, 150MHz	7c	Mat	2SC3671, 2SD1145, 2SD1244, 2SD2249, ++
2SD966	Si-N	=2SD965: 1W	7c(9mm)	Mat	2SD1934, 2SD1981
2SD967	Si-N-Darl	Uni, 30V, 0,2A, 0,4W, B=7000	9c	Mat	BC517, BC617, BC875, MPS-A13..14, ++
2SD968	Si-N	SMD, NF, 100V, 0,5A, 120MHz	39b	Mat	BCX56, 2SC2881, 2SC3438, 2SD1005..1007
2SD968A	Si-N	=2SD968: 120V	39b		2SC2881, 2SD1007, 2SD1418..1419
2SD969	Si-N	NF, Io-sat, 25V, 0,5A, 0,6W, 150MHz	9c	Mat	12SD1207, 2SD1246..47, (BC337..338)
2SD970	Si-N-Darl+Di	NF/S-L, 120V, 6A, 40W, B>1000	17c(A)	Hit	BD651, BDT21, BDW73D, BDX53D
2SD971	Si-N-Darl	S-L, 300/300V, 6A, 50W, B=2000	17j	Sak	BU910..912, 2SD1068..1069, 2SD1307, ++
2SD972	Si-N-Darl	NF/S-L, 50V, 4A, 30W, B=3000	17c(H)	Sak	BD715, BDW23A, BDW53A, BDW63A, ++
2SD973	Si-N	NF-Tr/E, 30V, 1A, 1W, 200MHz	9c	Mat	BC337..338, BC635, BC637, BC639, ++
2SD973A	Si-N	=2SD973: 80V	9c		BC337A, BC635, BC637, BC639, ++
2SD974	Si-N	S, TV, 120V, 1A, 0,9W	7c(9mm)	Hit	2SC2363, 2SC3228, 2SD887(A), 2SD1812, ++
2SD975	Si-N	S-L, TV-HA, 150V, 2A	14h	Hit	2SD781
2SD976	Si-N	HV, 700/400V, 7A, 50W	17c	Hit	BU406..406, 2SD884..885, 2SD1163, ++
2SD976A	Si-N	=2SD976: 350/150V	17j		BU406, BU406, 2SC3175, 2SC3591
2SD977	Si-N-Darl	S-L, 450/350V, 4A, 40W, B=300, <1/25µs	17j	Say	BU911..912, 2SD987, 2SD1072, 2SD1245, ++
2SD978	Si-N-Darl	=2SD977: 5A, B>400	17j		BU911..912, 2SD987, 2SD1072, 2SD1245, ++
2SD979	Si-N-Darl	S-L, 450/350V, 10A, 100W, B=900	77c(A)	Say	BU921..922, BUW81(A), 2SD685, ++
2SD980	Si-N-Darl	=2SD979: 7A	18j	Say	BU921..922, BUW81(A), 2SD707, ++
2SD981	Si-N-Darl	Reg-L, 200/180V, 5A, 100W, B=3000	23a	Fjd	2SD778, 2SD920..921, 2SD929, 2SD931, ++
2SD982	Si-N-Darl	=2SD981: 40W	17j	Fjd	2SD930, 2SD1023, 2SD1025, 2SD1756
2SD983	Si-N-Darl	=2SD981: 150/100V, 40W	17j	Fjd	BDX53F, 2SD630, 2SD1128, 2SD1169, ++
2SD985	Si-N-Darl+Di	NF/S-L, 150/80V, ±1,5A, 10W, B>2000	14h	Nec	2SD2019
2SD986	Si-N-Darl+Di	=2SD985: 150/80V	14h	Nec	2SD2019
2SD987	Si-N-Darl+Di	S-L, 500/400V, ±5A, 40W, B>200	17j	Nec	BU912, 2SD798..799, 2SD1245
2SD990	Si-N-Darl	NF/S-L, 100V, 3A, 30W, B>500	17j	Hit	BDW23C, BDW53C, BDW63C, 2SD637B, ++
2SD991	Si-N-Darl+Di	int.Z-Diode, 300/300V, 8A, 50W, B>500	17j	Hit	(2SD971, 2SD1071, 2SD1068..69, 2SD1113+)
2SD992(Z)	Si-N	NF/S-L, Io-sat, 30V, 2A, 10W	30j	Nec	2SC3076, 2SD1801..02
2SD993	Si-N+Di	CTV-HA, 1500/600V, 6A, 50W	23a	Say	BU208D, 2SC3480, 2SD1171..75, 2SD1654, ++
2SD994	Si-N+Di	CTV-HA, 1500/600V, 6A, 50W	23a	Say	BU508D, BU2508D, 2SC3683
2SD995	Si-N+Di	CTV-HA, 2500/900V, 8A, 50W	23a	Say	—
2SD997	Si-N	NF/S-L, 250/200V, 10A, 200W, 15MHz	23a	Nec	BUX17(AC), 2SC1596, 2SD555, 2SD583
2SD998	Si-N-Darl	NF/S-L, 100V, 1,5A, 10W, B=7000	14h	Nec	BD881, 2SD1376
2SD999	Si-N	SMD, Uni, 80V, 1A, 130MHz	39b	Nec	BC868, BCX54, BCX68, 2SC2883, ++
2SF1168(A)	50Hz-Thy	200(A=400)V, 6A, Igt/Ih<25/15mA	22a	Mat	MCR218, TAG625-.., TAG651-.., ++
2SF1188	F-Thy	TV-HA, +650V, 3,2A(Tc=60°C), Igt<30mA	22a	Say	S3703, (TD3F700H, TD4F700H, ++)
2SF1189	F-Thy	TV-HA, +600V, 3,2A(Tc=60°C), Igt<40mA	22a	Say	S3702, (TD3F800R, TD4F800R, ++)
2SF1418C..G	F-Thy	200..600V, 3,2A(60°), Igt<35mA, <4,3µs	22a	Say	BTW27S/.., T3S.., TAG670..671S-..
2SF1418C..G	F-Thy				—
2SF1420D..G	F-Thy	300..700V, 3,2A(75°), Igt/Ih<35/<30mA	22a	Say	BTW27S/.., T3S.., TAG670..671S-..
2SF1420D..G	F-Thy				—
2SF1450-200..600	50Hz-Thy	=CP8C..G		Hit	→CP8

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2SF1451-200..600	50Hz-Thy	=CP9C..G		Hit	→CP9..
2 SH		**2 SH**			
2SH11	UJT-P	35V, 50mA, Ip<12µA, Iv>7mA	2b	Nec, Tho	—
2SH11	MOS-N-IGBT	Iso-Gate Trans., 600V, 10A	17	Hit	—
2SH12	UJT-P	=2SH11	2b	Nec, Tho	—
2SH12	MOS-N-IGBT	Iso-Gate Trans, 600V, 15A	17	Hit	—
2SH13	UJT-P	55V, 50mA, Ip<6µA, Iv>11mA	2b	Tos	—
2SH13	MOS-N-IGBT	Iso-Gate Trans, 600V, 20A	17	Hit	—
2SH14	UJT-P	=2SH13: Ip<8µA, Iv>8mA	2b	Tos	—
2SH14	MOS-N-IGBT	Iso-Gate Trans, 600V, 30A	18	Hit	—
2SH15	UJT-P	30V, 50mA, Ip<12µA, Iv>7mA	2b	Tos	—
2SH15	MOS-N-IGBT	Iso-Gate Trans., 600V, 50A	18	Hit	—
2SH18	MOS-N-IGBT	Iso-Gate Trans., 600V, 75A	18	Hit	—
2SH16(A)	UJT-P	30V, 50mA, Ip<12µA, Iv>4mA	7q	Nec, Tho	2N2646P
2SH17	UJT-P	=2SH16: Ip<4µA, Iv>2mA	7q	Nec, Tho	—
2SH17	MOS-N-IGBT	Iso-Gate Trans, 600V, 12A	17	Hit	—
2SH18	UJT-P	=2SH16: 0,3W	2b, 5e	Gen, Mot	—
2SH18	MOS-N-IGBT	Iso-Gate Trans, 600V, 18A	17	Hit	—
2SH19	UJT-P	=2SH17: 0,3W	2b, 5e	Gen, Mot	—
2SH19	MOS-N-IGBT	Iso-Gate Trans., 600V, 24A	17	Hit	—
2SH20	UJT-P	55V, 50mA, Ip<3,5µA, Iv>6mA	2b	Tos	—
2SH20	MOS-N-IGBT	Iso-Gate Trans., 600V, 36A	18	Hit	—
2SH21	UJT-P	=2SH20: Ip<4µA, Iv>4mA	2b	Tos	—
2SH21	MOS-N-IGBT	Iso-Gate Trans., 600V, 50A	18	Hit	—
2SH22	UJT-P	25V, 50mA, Ip<4µA, Iv>4mA	2b	Tos	2SH21
2SH22	MOS-N-IGBT	Iso-Gate Trans., 600V, 75A	18	Hit	—
2SH23	UJT-P	25V, 100mA, Ip<4µA, Iv>7mA	2b	Nec	2SH20
2SH24	UJT-P	=2SH23: Ip<12µA	2b	Nec	—
2SH25	UJT-P	=2SH23: 75mA, 0,3W	7b	Nec	—
2 SJ		**2 SJ**			
2SJ100	MOS-P-FET-e	=2SJ99: 160V	20p	Hit	(2SJ83)
2SJ101	MOS-P-FET-e	V-MOS, 40V, 5A, 30W, <0,4Ω, 60/100ns	17p	Hit	BUZ172, IRF9521, IRF9523, 2SJ153, ++
2SJ102	MOS-P-FET-e	=2SJ101: 60V	17p	Hit	BUZ172, IRF9521, IRF9523, 2SJ153, ++
2SJ103	P-FET	Analog-S, Uni, 50V, Idss>1,2mA, Up<6V	7e	Tos	2N5460, 2N5463, 2SJ105
2SJ104	P-FET	Analog-S, Uni, 25V, Idss>2,6mA, Up<2V	7a	Tos	2SJ107..108
2SJ105	P-FET	=2SJ103	41e	Tos	2N5460, 2N5463, 2SJ103
2SJ108	P-FET	=2SJ103: SMD	35f	Tos	—
2SJ107	P-FET	=2SJ104	41a	Tos	2SJ104, 2SJ108
2SJ108	P-FET	Uni, ra, 25V, Idss>1mA, Up<2V	41a	Tos	2SJ104, 2SJ107
2SJ109	P-FET	Dual, 30V, Idss=2,6..20mA, Up<2V	7-SQP	Tos	—
2SJ11	P-FET	Uni, 20V, Idss=0,05..0,9mA, Up<5V	5n	Tos	2N2606, 2N5797
2SJ110	P-FET	Analog-S, Uni, 25V, Idss=5..30, Up<2V	7a	Tos	2SJ72
2SJ111	P-FET	NF/S, ra, 25V, Idss=5..30, Up<2V	7a	Tos	2SJ72
2SJ112	MOS-P-FET-e	V-MOS, 100V, 10A, 100W, <0,35Ω(5A)	23a	Hit	2SJ131, 2SJ200
2SJ113	MOS-P-FET-e	=2SJ112	18p	Hit	2SJ131, 2SJ200
2SJ114	MOS-P-FET-e	=2SJ112: 200V, 8A	18p	Hit	—
2SJ115	MOS-P-FET-e	V-MOS, NF-L, 160V, 8A, 100W, <1,4Ω	18p	Tos	2SJ114, 2SJ119
2SJ116	MOS-P-FET-e	V-MOS, 400V, 8A, 125W, <2,25Ω, 60/220ns	23a	Hit	—
2SJ117	MOS-P-FET-e	V-MOS, 400V, 2A, 40W, <7Ω(1A), 35/80ns	17p, d(?)	Hit	—
2SJ118	MOS-P-FET-e	V-MOS, 140V, 8A, 100W, <4Ω(4A), 70/160ns	18p	Hit	2SJ114..115
2SJ119	MOS-P-FET-e	=2SJ118: 160V	18p	Hit	2SJ114..115
2SJ12	P-FET	=2SJ11: Idss=0,09..0,9mA	5n	Tos	2N2606, 2N5797
2SJ120(L,S)	MOS-P-FET-e	V-MOS, 40V, 2A, 10W, <1,5Ω(1A), 35/40ns	30p	Hit	2SJ128, 2SJ133, 2SJ191, 2SJ194
2SJ122	MOS-P-FET-e	V-MOS, 60V, 10A, 50W, <0,2Ω, 80/200ns	17p	Hit	IRF9531, IRF9533, 2SJ136, 2SJ169, ++
2SJ123	MOS-P-FET-e	V-MOS-L, 70V, 10A, 30W, <0,4Ω	17p	Tos	2SJ170, 2SJ136
2SJ125	P-FET	SMD, Uni, 50V, Idss=1..12mA, Up<6V	35f	Mit	—
2SJ126	MOS-P-FET-e	V-MOS-L, 60V, 10A, 40W, <0,4Ω(5A)	17c	Tos	2SJ137, 2SJ147, 2SJ175, 2SJ236
2SJ127	MOS-P-FET-e*	V-MOS, 120V, 10A, 50W, 0,25Ω, 110/240ns	17p	Hit	IRF9640, IRF9641
2SJ128(Z)	MOS-P-FET-e	V-MOS, S-L, 100V, ±2A, 20W, <1Ω(1A)	30p	Nec	2SJ194
2SJ129	P-FET	NF-V, 50V, 20mA, Idss=0,5..14mA, Up<3V	40e	Mat	2N5021, 2SJ74
2SJ13	P-FET	Uni, 20V, Idss=1..12mA, Up<6V	2a(G=case)	Tos	—
2SJ130(L,S)	MOS-P-FET-e*	V-MOS, 300V, 1A, 20W, <8,5Ω, 35/80ns	79p	Hit	—
2SJ131	MOS-P-FET-e	V-MOS, S-L, 170V, 10A, 100W	18c(p)	Son	2SJ200
2SJ132(Z)	MOS-P-FET-e	V-MOS, S-L, 30V, ±2A, 20W, <0,4Ω(1A)	30p	Nec	2SJ120, 2SJ191

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2SJ133(Z)	MOS-P-FET-e	V-MOS, S-L, 60V, ±2A, 20W, <0,8Ω(1A)	30p	Nec	2SJ191
2SJ134	MOS-P-FET-e	V-MOS, S-L, 100V, ±6A, 40W, <0,6Ω(3,5A)	17p	Nec	IRF9630..9633
2SJ135	MOS-P-FET-e	=2SJ134: Iso, ±5A, 30W	17c	Nec	2SJ154
2SJ136	MOS-P-FET-e	V-MOS, S-L, 60V, ±12A, 40W, <0,3Ω(6,5A)	17p	Nec	IRF9541, IRF9543, 2SJ140, 2SJ173
2SJ137	MOS-P-FET-e	=2SJ136: Iso, ±10A, 30W	17c	Nec	2SJ147, 2SJ175
2SJ138	MOS-P-FET-e	V-MOS, S-L, 100V, ±12A, 60W, <0,3Ω(6,5A)	17p	Nec	IRF9540, IRF9542, 2SJ127
2SJ139	MOS-P-FET-e	=2SJ138: Iso, ±10A, 35W	17c	Nec	2SJ274
2SJ140	MOS-P-FET-e	V-MOS, S-L, 60V, ±19A, 60W, <0,2Ω(10A)	17p	Nec	2SJ174, 2SJ221
2SJ141	MOS-P-FET-e	=2SJ140: Iso, ±13A, 35W	17c	Nec	2SJ176, 2SJ293
2SJ142	MOS-P-FET-e	V-MOS, S-L, 100V, ±13A, 35W, <0,2Ω(10A)	17c	Nec	2SJ222
2SJ143	MOS-P-FET-e	V-MOS, S-L, 60V, ±16A, 35W, <0,15Ω(10A)	17c	Nec	2SJ176..177, 2SJ240
2SJ144	P-FET	SMD, Uni, 50V, Idss=1,2..14mA, Up<6V	35f(2mm)	Tos	—
2SJ145	P-FET	=2SJ125	35f(2mm)	Mit	—
2SJ146	MOS-P-FET-e	SMD, S, 50V, 0,1A, <40/60ns, <150Ω	35a	Mat	BSS84, 2SJ185, 2SJ209..210
2SJ147	MOS-P-FET-e	V-MOS, 60V, 12A, 40W, 0,2Ω, 65/160ns	17c	Tos	2SJ141, 2SJ175..176, 2SJ265
2SJ148	MOS-P-FET-e	S, 60V, 0,2A, 0,4W, <2Ω(50mA), 14/100ns	7c	Tos	BST100
2SJ15	P-FET	Uni, 18V, Idss=1,5mA, Up<6V	2a(G=case)	Fui	2N5460, 2N5463, 2SJ103, 2SJ105
2SJ151	MOS-P-FET-e*	V-MOS, S-L, 100V, ±3A, 35W, <1,2Ω(1,5A)	17p	Nec	IRF9510, IRF9620..9623
2SJ152	MOS-P-FET-e*	=2SJ151: Iso, 30W	17c	Nec	2SJ135, 2SJ157
2SJ153	MOS-P-FET-e*	V-MOS, S-L, 60V, ±6A, 40W, <0,6Ω(3,5A)	17p	Nec	—
2SJ154	MOS-P-FET-e*	=2SJ153: Iso, ±5A, 30W	17c	Nec	аналог 2SJ137, 2SJ147, 2SJ175
2SJ155	MOS-P-FET-e	V-MOS, S-L, 50V, 3A, 30W, <0,65Ω(2A)	17c	Mat	2SJ152
2SJ156	MOS-P-FET-e	V-MOS, S-L, 50V, 5A, 30W, <0,22Ω(3A)	17c	Mat	2SJ135, 2SJ154
2SJ157	MOS-P-FET-e	V-MOS, S-L, 100V, 3A, 30W, <1,6Ω(2A)	17c	Mat	2SJ135, 2SJ152
2SJ158	MOS-P-FET-e	V-MOS, S-L, 100V, 5A, 30W, <0,55Ω(3A)	17c	Mat	2SJ135, 2SJ154
2SJ159	MOS-P-FET-e	V-MOS, S-L, 160V, 3A, 30W, <1Ω(2A)	17c	Mat	2SJ308
2SJ16	P-FET	Uni, 16V, Idss=1,5mA, Up<6V	2a(G=case)	Fui	2N5460, 2N5463, 2SJ103, 2SJ105
2SJ160	MOS-P-FET-e*	V-MOS, S-L, 120V, 7A, 100W, 230/110ns	18d,p(?)	Hit	(2SJ115, 2SJ116..119)
2SJ161	MOS-P-FET-e*	=2SJ160: 140V	18d,p(?)	Hit	(2SJ115, 2SJ116..119)
2SJ162	MOS-P-FET-e*	=2SJ160: 160V	18d,p(?)	Hit	(2SJ115, 2SJ119)
2SJ163	P-FET	=2SJ164: SMD	35f	Mat	—
2SJ164	P-FET	65V, 20mA, Idss=0,2..6mA, Up<3,5V	40a	Mat	2N5020
2SJ165	MOS-P-FET-e*	V-MOS, 50V, ±0,1A, 0,25W, <50Ω(20mA)	40c	Nec	BSS110, 2SJ146
2SJ166	MOS-P-FET-e*	=2SJ165: SMD	35a	Nec	BSS84, 2SJ165
2SJ167	MOS-P-FET-e	=2SJ148: 0,3W	41c	Tos	BST100
2SJ168	MOS-P-FET-e	=2SJ148: SMD	35a	Tos	2SJ209..211
2SJ169	MOS-P-FET-e	V-MOS, S-L, 60V, 12A, 50W, <0,35Ω(6,5A)	17p	Hit	2SJ122..123, 2SJ172
2SJ17	P-FET	NF, re, 20V, Idss>0,11mA	40d	Son	—
2SJ170	MOS-P-FET-e	V-MOS, S-L, 60V, 12A, 50W, <0,35Ω(6,5A)	17p	Hit	2SJ127, 2SJ138
2SJ171	MOS-P-FET-e	V-MOS, S-L, 50V, 9,7A, 40W, <0,26Ω(5,6A)	17p	Hit	BUZ171, 2SJ122..123, 2SJ136, 2SJ172
2SJ172	MOS-P-FET-e*	V-MOS, LogL, 60V, 10A, 40W, <0,16Ω(5A)	17p	Hit	2SJ290, 2SJ302
2SJ173	MOS-P-FET-e*	V-MOS, LogL, 60V, 15A, 50W, <0,11Ω(6A)	17p	Hit	2SJ221, 2SJ290, 2SJ302
2SJ174	MOS-P-FET-e*	V-MOS, LogL, 60V, 20A, 75W, <0,065Ω(10A)	17p	Hit	2SJ221, 2SJ291
2SJ175	MOS-P-FET-e*	=2SJ172: Iso, 25W	17c	Hit	2SJ236
2SJ176	MOS-P-FET-e*	=2SJ173: Iso, 30W	17c	Hit	2SJ293, 2SJ321
2SJ177	MOS-P-FET-e*	=2SJ174: Iso, 35W	17c	Hit	2SJ294, 2SJ322
2SJ178	MOS-P-FET-e*	V-MOS, S, 30V, ±1A, 0,75W, <1Ω(0,5A)	7b	Nec	2SJ196
2SJ179	MOS-P-FET-e*	=2SJ178: SMD, ±1,5A	39b	Nec	2SJ190, 2SJ197, 2SJ236
2SJ18	P-FET	V-FET-L, 170V, 5A, 63W, 16Ω	23a	Son	—
2SJ180	MOS-P-FET-e*	=2SJ178: 1W	9c	Nec	2SJ196
2SJ181(L,S)	MOS-P-FET-e*	V-MOS, 600V, 0,5A, 20W, <25Ω(0,3A)	79p	Hit	—
2SJ182(L,S)	MOS-P-FET-e*	V-MOS, LogL, 60V, 3A, 20W, <0,4Ω(2A)	30p	Hit	2SJ235
2SJ183	MOS-P-FET-e*	V-MOS, 60V, 5A, 20W, <0,35Ω(2,5A)	30p	Tos	2SJ192, 2SJ239, 2SJ245, 2SK279
2SJ184	MOS-P-FET-e*	V-MOS, S, 50V, ±0,1A, 0,25W, <40Ω(1mA)	40c	Nec	BSS110
2SJ185	MOS-P-FET-e*	=2SJ184: SMD	35a	Nec	BSS84
2SJ186	MOS-P-FET-e*	V-MOS, 200V, 0,5A, <12Ω(0,25A), 12/32ns	39j	Hit	—
2SJ187	MOS-P-FET-e*	SMD, V-MOS, LogL, 30V, 1A, <0,75Ω(0,5A)	39b	Say	2SJ190, 2SJ278
2SJ188	MOS-P-FET-e*	V-MOS, LogL, 30V, 2A, 20W, <0,3Ω(1A)	30c	Say	2SJ191, 2SJ194
2SJ189	MOS-P-FET-e*	V-MOS, LogL, 30V, 4A, 30W, <0,12Ω(2A)	30c	Say	2SJ192, 2SJ245, 2SJ279
2SJ19	P-FET	V-FET, NF, 140V, 0,1A, 0,6W	2a	Nec	—
2SJ190	MOS-P-FET-e*	SMD, V-MOS, LogL, 60V, 1A, <1,2Ω(0,5A)	39b	Say	2SJ278
2SJ191	MOS-P-FET-e*	V-MOS, LogL, 60V, 2A, 20W, <0,45Ω(1A)	30c	Say	2SJ235
2SJ192	MOS-P-FET-e*	V-MOS, LogL, 60V, 4A, 30W, <0,2Ω(2A)	30c	Say	2SJ245, 2SJ279
2SJ193	MOS-P-FET-e*	SMD, V-MOS, LogL, 100V, 1A, <2,4Ω(0,5A)	39b	Say	—
2SJ194	MOS-P-FET-e*	V-MOS, LogL, 100V, 2A, 20W, <0,95Ω(1A)	30c	Say	2SJ195
2SJ195	MOS-P-FET-e*	V-MOS, LogL, 100V, 4A, 30W, <0,4Ω(2A)	30c	Say	—

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2SJ196	MOS-P-FET-e*	V-MOS, S, 60V, ±1A, 0,75W, <1Ω(0,5A)	7b	Nec	—
2SJ197	MOS-P-FET-e*	=2SJ196: SMD	39b	Nec	2SJ190, 2SJ238
2SJ196	MOS-P-FET-e*	V-MOS, S, 100V, ±0,5A, 0,75W, <2Ω(0,5A)	7b	Nec	2SJ231
2SJ199	MOS-P-FET-e*	=2SJ198 SMD	39b	Nec	2SJ213
2SJ20	P-FET	V-FET-L, 100V, 10A, 100W, 10Ω	23a	Nec	—
2SJ200	MOS-P-FET-e	V-MOS, NF-E, 160V, 10A, 120W	18p	Tos	—
2SJ201	MOS-P-FET-e	V-MOS, NF-E, 200V, 12A, 150W	77p	Tos	—
2SJ202	MOS-P-FET-e*	SMD, V-MOS, S, 16V, ±0, 1A, <30Ω(1mA)	35a(2mm)	Nec	—
2SJ203	MOS-P-FET-e*	SMD, V-MOS, S, 16V, ±0,2A, <10Ω(1mA)	35a	Nec	BSS84, 2SJ185
2SJ204	MOS-P-FET-e*	SMD, V-MOS, S, 30V, ±0,2A, <8Ω(10mA)	35a	Nec	BSS84, 2SJ185
2SJ205	MOS-P-FET-e*	SMD, V-MOS, S, 16V, ±0,5A, <3Ω(0,3A)	39b	Nec	2SJ212
2SJ206	MOS-P-FET-e*	SMD, V-MOS, S, 30V, ±0,5A, <3Ω(0,3A)	39b	Nec	2SJ212
2SJ207	MOS-P-FET-e*	SMD, V-MOS, S, 16V, ±1A, <1,5Ω(0,5A)	39b	Nec	2SJ190, 2SJ197, 2SJ238
2SJ206	MOS-P-FET-e*	SMD, V-MOS, S, 16V, ±2A, <1Ω(1A)	39b	Nec	—
2SJ209	MOS-P-FET-e*	SMD, V-MOS, S, 100V, ±0,1A, <60Ω(10mA)	35a	Nec	—
2SJ21	P-FET	V-FET-L, 160V, 15W, Idss=30..300	22a	Nec	—
2SJ210	MOS-P-FET-e*	SMD, V-MOS, S, 60V, ±0,2A, <10Ω(10mA)	35a	Nec	BSS84, 2SJ185
2SJ211	MOS-P-FET-e*	SMD, V-MOS, S, 100V, ±0,2A, <20Ω(10mA)	35a	Nec	—
2SJ212	MOS-P-FET-e*	SMD, V-MOS, S, 60V, ±0,5A, <3Ω(0,5A)	39b	Nec	2SJ199, 2SJ213
2SJ213	MOS-P-FET-e*	SMD, V-MOS, S, 100V, ±0,5A, <4,2Ω(0,3A)	39b	Nec	2SJ198
2SJ214(L,S)	MOS-P-FET-e*	V-MOS, LogL, 60V, 10A, 40W, <0,18Ω(5A)	30p	Hit	2SJ219, 2SJ296
2SJ215	MOS-P-FET-e*	V-MOS, LogL, 60V, 35A, 125W, <0,06Ω	18p	Hit	2SJ217
2SJ216	MOS-P-FET-e*	=2SJ215: Iso, 50W	≈18c	Hit	2SJ218
2SJ217	MOS-P-FET-e*	V-MOS, LogL, 60V, 45A, 150W, <0,042Ω	18c	Hit	—
2SJ218	MOS-P-FET-e*	=2SJ217: Iso, 60W	≈18c	Hit	—
2SJ219(L,S)	MOS-P-FET-e*	V-MOS, LogL, 60V, 15A, 50W, <0,11Ω(8A)	30p	Hit	2SJ268, 2SJ296
2SJ22	P-FET	NF, ra, 60V, Idss=0,3..0,7mA	2d	Son	—
2SJ220(L,S)	MOS-P-FET-e*	V-MOS, LogL, 60V, 20A, 75W, <0,065Ω(10A)	30p	Hit	2SJ297
2SJ221	MOS-P-FET-e*	V-MOS, LogL, 100V, 20A, 75W	17c	Hit	—
2SJ222	MOS-P-FET-e*	=2SJ221: Iso, 35W	15c	Hit	—
2SJ223(L,S)	MOS-P-FET-e*	V-MOS, LogL, 60V, 2A, 10W, <0,7Ω(1A)	30p	Hit	2SJ328
2SJ224	MOS-P-FET-e	V-MOS, 60V, 12A, 80W, <0,2Ω(6A)	30p	Tos	2SJ219, 2SJ296
2SJ225	MOS-P-FET-e	V-MOS, S, 30V, 1A, 1W, <0,75Ω(0,5A)	9c	Say	2SJ196
2SJ226	MOS-P-FET-e*	V-MOS, S, 30V, 2A, 1,5W, <0,3Ω(1A)	≈12b	Say	—
2SJ227	MOS-P-FET-e*	V-MOS, S, 30V, 3A, 1,5W, <0,13Ω(1,5A)	≈12b	Say	—
2SJ228	MOS-P-FET-e*	V-MOS, LogL, 60V, 0,8A, 1W, <1,2Ω(0,4A)	9c	Say	2SJ353
2SJ229	MOS-P-FET-e*	V-MOS, LogL, 60V, 1,6A, <0,45Ω(0,8W)	≈12b	Say	—
2SJ230	MOS-P-FET-e*	V-MOS, LogL, 60V, 2,5A, <0,21Ω(1,5A)	≈12b	Say	—
2SJ231	MOS-P-FET-e*	V-MOS, S, 100V, 0,5A, 1W, <2,4Ω(0,25A)	9c	Say	—
2SJ232	MOS-P-FET-e*	V-MOS, LogL, 100V, 1,2A, <0,95Ω(0,6A)	≈12b	Say	—
2SJ233	MOS-P-FET-e*	V-MOS, LogL, 100V, 1,8A, <0,4Ω(1A)	≈12b	Say	—
2SJ234(L,S)	MOS-P-FET-e*	V-MOS, LogL, 30V, 2,5A, 10W, <0,4Ω(1,4A)	30p	Hit	2SJ191
2SJ235(L,S)	MOS-P-FET-e*	V-MOS, LogL, 60V, 3A, 20W, <0,4Ω(2A)	30p	Hit	(2SJ182)
2SJ235(L,S)	MOS-P-FET-e*	integr. Rgate			—
2SJ238	MOS-P-FET-e*	V-MOS, LogL, 60V, 10A, 25W, <0,18Ω(5A)	17c	Hit	(2SJ176)
2SJ238	MOS-P-FET-e*	integr. Rgate			—
2SJ237	MOS-P-FET-e*	V-MOS, LogL, 60V, 15A, 30W, <0,11Ω(8A)	17c	Hit	(2SJ177, 2SJ293)
2SJ237	MOS-P-FET-e*	integr. Rgate			—
2SJ238	MOS-P-FET-e	SMD, V-MOS, 60V, 1A, <0,85Ω(0,5A)	39b	Tos	2SJ190, 2SJ193, 2SJ197
2SJ239	MOS-P-FET-e	V-MOS, 60V, 5A, 20W, <0,25Ω(2,5A)	30p	Tos	2SJ183, 2SJ192, 2SJ195
2SJ240	MOS-P-FET-e	V-MOS, 60V, 20A, 45W, <0,045Ω(10A)	17c	Tos	2SJ177, 2SJ294, 2SJ322
2SJ241	MOS-P-FET-e	=2SJ240: 100W	30p	Tos	—
2SJ243	MOS-P-FET-e*	SMD, V-MOS, S, 30V, ±0,1A, <25Ω(10mA)	35(1,6mm)	Nec	—
2SJ244	MOS-P-FET-e*	SMD, V-MOS, LogL, 12V, 2A, <0,9Ω(0,5A)	39j	Hit	(2SJ317)
2SJ244	MOS-P-FET-e*	integr. Rgate	39j		—
2SJ245(L,S)	MOS-P-FET-e*	V-MOS, LogL, 60V, 5A, 20W, <0,25Ω(3A)	30p	Hit	2SJ192, 2SJ279
2SJ248(L,S)	MOS-P-FET-e*	V-MOS, LogL, 30V, 7A, 20W, <0,17Ω(4A)	30p	Hit	2SJ333
2SJ247	MOS-P-FET-e*	V-MOS, LogL, 100V, 8A, 40W, <0,3Ω(4A)	17c	Hit	—
2SJ248	MOS-P-FET-e*	=2SJ247: Iso, 25W	15c	Hit	2SJ350
2SJ249	MOS-P-FET-e	V-MOS, L, 100V, 15A, 45W, <0,18Ω(7A)	17c	Tos	2SJ142, 2SJ222
2SJ250	MOS-P-FET-e*	V-MOS, LogL, 60V, 10A, 12W, <0,19Ω(5A)	14b	Hit	—
2SJ251	MOS-P-FET-e	V-MOS, LogL, 30V, 10A, 50W, <0,17Ω(5A)	17p	Say	2SJ172
2SJ252	MOS-P-FET-e	V-MOS, LogL, 30V, 12A, 60W, <0,13Ω(8A)	17p	Say	2SJ173, 2SJ290
2SJ253	MOS-P-FET-e	V-MOS, LogL, 30V, 20A, 70W, <75mΩ(10A)	17p	Say	2SJ174, 2SJ291
2SJ254	MOS-P-FET-e*	V-MOS, LogL, 30V, 8A, 25W, <0,12Ω(5A)	17c	Say	2SJ175, 2SJ238
2SJ255	MOS-P-FET-e*	V-MOS, LogL, 30V, 10A, 25W, <95mΩ(8A)	17c	Say	2SJ175, 2SJ238

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2SJ256	MOS-P-FET-e*	V-MOS, LogL, 30V, 18A, 30W, <55mΩ(10A)	17c	Say	2SJ177, 2SJ294, 2SJ374
2SJ257	MOS-P-FET-e*	V-MOS, LogL, 30V, 10A, 50W, <0,12Ω(5A)	30p	Say	2SJ214
2SJ258	MOS-P-FET-e*	V-MOS, LogL, 30V, 12A, 60W, <95mΩ(6A)	30p	Say	2SJ214
2SJ259	MOS-P-FET-e*	V-MOS, LogL, 30V, 20A, 70W, <55mΩ(10A)	30p	Say	2SJ409
2SJ260	MOS-P-FET-e	V-MOS, LogL, 60V, 6A, 50W, <0,27Ω(4A)	17p	Say	2SJ172
2SJ261	MOS-P-FET-a	V-MOS, LogL, 60V, 10A, 60W, <0,2Ω(5A)	17p	Say	2SJ172
2SJ262	MOS-P-FET-a	V-MOS, LogL, 60V, 16A, 70W, <0,11 Ω(9A)	17p	Say	2SJ174, 2SJ291
2SJ263	MOS-P-FET-e*	V-MOS, LogL, 60V, 6A, 25W, <0,2Ω(4A)	17c	Say	2SJ175, 2SJ236
2SJ264	MOS-P-FET-e*	V-MOS, LogL, 60V, 6A, 25W, <0,15Ω(5A)	17c	Say	2SJ175, 2SJ236
2SJ265	MOS-P-FET-e*	V-MOS, LogL, 60V, 15A, 30W, <0,11Ω(9A)	17c	Say	2SJ176, 2SJ293
2SJ266	MOS-P-FET-e*	V-MOS, LogL, 60V, 6A, 50W, <0,2Ω(4A)	30p	Say	2SJ214
2SJ267	MOS-P-FET-e*	V-MOS, LogL, 60V, 10A, 60W, <0,15Ω(5A)	30p	Say	2SJ214
2SJ268	MOS-P-FET-e*	V-MOS, LogL, 60V, 16A, 70W, <0,08Ω(9A)	30p	Say	2SJ409
2SJ269	MOS-P-FET-e	V-MOS, LogL, 100V, 6A, 50W, <0,55Ω(3A)	17p	Say	—
2SJ270	MOS-P-FET-e	V-MOS, LogL, 100V, 6A, 60W, <0,4Ω(4A)	17p	Say	2SJ247
2SJ271	MOS-P-FET-e	V-MOS, LogL, 100V, 15A, 70W, <0,22Ω(6A)	17p	Say	2SJ221
2SJ272	MOS-P-FET-e*	V-MOS, LogL, 100V, 4A, 25W, <0,4Ω(3A)	17c	Say	2SJ248
2SJ273	MOS-P-FET-e*	V-MOS, LogL, 100V, 6A, 25W, <0,3Ω(4A)	17c	Say	2SJ248
2SJ274	MOS-P-FET-e*	V-MOS, LogL, 100V, 12A, 30W, <0,16Ω(8A)	17c	Say	2SJ222
2SJ275	MOS-P-FET-e*	V-MOS, LogL, 100V, 6A, 50W, <0,4Ω(3A)	30p	Say	—
2SJ276	MOS-P-FET-e*	V-MOS, LogL, 100V, 6A, 50W, <0,3Ω(4A)	30p	Say	—
2SJ277	MOS-P-FET-e*	V-MOS, LogL, 100V, 15A, 70W, <0,16Ω(6A)	30p	Say	2SJ409
2SJ278	MOS-P-FET-e*	SMD, V-MOS, LogL, 60V, 1A, <0,83Ω(0,5A)	39j	Hit	2SJ190
2SJ279(L,S)	MOS-P-FET-e*	V-MOS, LogL, 60V, 5A, 20W, <0,2Ω(3A)	30p	Hit	2SJ245
2SJ280(L,S)	MOS-P-FET-a*	V-MOS, LogL, 60V, 30A, 75W, <43mΩ(15A)	30p	Hit	—
2SJ281	MOS-P-FET-e	V-MOS, 250V, 3A, 30W, <2,6Ω	30p	Say	—
2SJ282	MOS-P-FET-e	V-MOS, LogL, 250V, 3A, 50W, <2Ω(1,5A)	17p	Say	—
2SJ283	MOS-P-FET-e	V-MOS, 120V, 5A, 25W, <1,4Ω	17c	Tos	2SJ350
2SJ284	MOS-P-FET-e	V-MOS, LogL, 30V, 0,3A, <2,2Ω(0,15A)	35a	Say	—
2SJ285	MOS-P-FET-e	V-MOS, LogL, 60V, 0,25A, <3Ω(0,15A)	35a	Say	2SJ210..211
2SJ286	MOS-P-FET-e	V-MOS, LogL, 100V, 0,15A, <7Ω(0,1A)	35a	Say	2SJ209, 2SJ211
2SJ287	MOS-P-FET-e*	V-MOS, LogL, 30V, 0,5A, <2,2Ω(0,25A)	39b	Say	2SJ190, 2SJ278
2SJ288	MOS-P-FET-e*	SMD, V-MOS, LogL, 60V, 0,5A, <3Ω(0,25A)	39b	Say	2SJ190, 2SJ278
2SJ289	MOS-P-FET-e*	SMD, V-MOS, LogL, 100V, 0,5A, <7,5Ω	39b	Say	2SJ193
2SJ29	P-FET	V-FET-L, 140V, 10A, 100W, 15Ω	23a	Hit	—
2SJ290	MOS-P-FET-e*	V-MOS, LogL, 60V, 15A, 50W, <95mΩ(6A)	17p	Hit	2SJ173, 2SJ221
2SJ291	MOS-P-FET-e*	V-MOS, LogL, 60V, 20A, 60W, <65mΩ(10A)	17p	Hit	2SJ174, 2SJ221
2SJ292	MOS-P-FET-e*	=2SJ280:	17p	Hit	—
2SJ293	MOS-P-FET-e*	=2SJ290: Iso, 30W	17c	Hit	2SJ176, 2SJ321
2SJ294	MOS-P-FET-a*	=2SJ291: Iso, 35W	17c	Hit	2SJ177, 2SJ322
2SJ295	MOS-P-FET-e*	=2SJ280: Iso, 35W	17c	Hit	2SJ323
2SJ296(L,S)	MOS-P-FET-e*	=2SJ290:	=30p	Hit	2SJ219
2SJ297(L,S)	MOS-P-FET-e*	=2SJ290:	30p	Hit	2SJ220
2SJ298	MOS-P-FET-e*	V-MOS, LogL, 20V, 5A, 12W, <0,12Ω(3A)	14b	Hit	2SJ250
2SJ299	MOS-P-FET-e*	=2SJ298:	30p	Hit	2SJ245, 2SJ279, 2SJ318
2SJ300	MOS-P-FET-e*	V-MOS, LogL, 20V, 10A, 12W, <0,08Ω(5A)	14b	Hit	2SJ250
2SJ302	MOS-P-FET-e*	V-MOS, 60V, 16A, 75W, <0,1Ω(8A)	17p	Nec	2SJ173, 2SJ221, 2SJ290
2SJ302Z	MOS-P-FET-e*	=2SJ302:	30p		2SJ268
2SJ303	MOS-P-FET-e*	V-MOS, 60V, 14A, 35W, <0,1Ω(7A)	17c	Nec	2SJ143, 2SJ176, 2SJ265, 2SJ304
2SJ304	MOS-P-FET-e	V-MOS, LogL, 60V, 14A, 40W, <0,12Ω(7A)	17c	Tos	2SJ178, 2SJ265, 2SJ303
2SJ305	MOS-P-FET-e*	V-MOS, 30V, 0,2A, <4Ω(0,05A)	35a	Say	2SJ210..211
2SJ306	MOS-P-FET-e*	V-MOS, 250V, 3A, 25W, <2Ω(1,5A)	17c	Say	2SJ307
2SJ307	MOS-P-FET-e*	V-MOS, 250V, 6A, 30W, <3Ω(3A)	17c	Say	2SJ308
2SJ308	MOS-P-FET-e*	V-MOS, 250V, 9A, 40W, <0,48Ω(5A)	17c	Say	—
2SJ312	MOS-P-FET-a	=2SJ304:	30p	Tos	2SJ268
2SJ313	MOS-P-FET-e	V-MOS, LogL, 180V, 1A	17c	Tos	—
2SJ314-01(L,S)	MOS-P-FET-e	V-MOS, LogL, 60V, 5A, 20W, <0,03Ω(2,5A)	30p	Fjd	2SJ192, 2SJ279
2SJ315	MOS-P-FET-e	V-MOS, LogL, 60V, 5A, 20W, <0,25Ω(2,5A)	30p	Tos	2SJ192, 2SJ279
2SJ316	MOS-P-FET-e*	V-MOS, LogL, 12V, 1A, <0,42Ω(0,5A)	39b	Tos	2SJ190, 2SJ278
2SJ317	MOS-P-FET-e*	SMD, V-MOS, LogL, 12V, ±2A, <0,7Ω(0,5A)	39j	Hit	(2SJ244)
2SJ317	MOS-P-FET-e*	integr. Rgate			—
2SJ318(L,S)	MOS-P-FET-e*	V-MOS, LogL, 20V, 5A, 20W, <0,13Ω(3A)	30p	Hit	2SJ245, 2SJ279, 2SJ299
2SJ319(L,S)	MOS-P-FET-e*	V-MOS, 200V, 3A, 20W, <2,3Ω(2A)	79p	Hit	—
2SJ32	P-FET	NF/S, 150V, 0,6W, 350Ω		Shi	—
2SJ320	MOS-P-FET-e*	V-MOS, LogL, 250V, 4A, 25W, <1,3Ω(2A)	17c	Say	—
2SJ321	MOS-P-FET-e*	V-MOS, LogL, 60V, 15A, 30W, <95mΩ(6A)	17c	Hit	2SJ176, 2SJ293

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2SJ322	MOS-P-FET-e*	V-MOS, LogL, 60V, 20A, 35W, <65mΩ(10A)	17c	Hit	2SJ177, 2SJ294
2SJ323	MOS-P-FET-e*	V-MOS, LogL, 60V, 30A, 35W, <43mΩ(15A)	17c	Hit	2SJ295
2SJ324(Z)	MOS-P-FET-e*	V-MOS, LogL, 30V, ±2A, 20W, <0,25Ω(1A)	30p	Nec	2SJ326
2SJ325(Z)	MOS-P-FET-e*	V-MOS, LogL, 30V, ±4A, 20W, <0,11Ω(2A)	30p	Nec	2SJ245, 2SJ327
2SJ326(Z)	MOS-P-FET-e*	V-MOS, LogL, 60V, ±2A, 20W, <0,37Ω(1A)	30p	Nec	2SJ191
2SJ327(Z)	MOS-P-FET-e*	V-MOS, LogL, 60V, ±4A, 20W, <0,17Ω(2A)	30p	Nec	2SJ192, 2SJ245, 2SJ327
2SJ328	MOS-P-FET-e*	V-MOS, LogL, 60V, ±20A, 75W, <65mΩ(10A)	17p	Nec	2SJ174, 2SJ221
2SJ328Z	MOS-P-FET-e*	=2SJ328	30p		2SJ409
2SJ329	MOS-P-FET-e*	V-MOS, LogL, 60V, ±15A, 35W, <0,06Ω(8A)	17c	Nec	2SJ176, 2SJ265, 2SJ293
2SJ33	P-FET	=2SJ32: 200V		Shi	—
2SJ330	MOS-P-FET-e*	V-MOS, LogL, 60V, ±20A, 35W, <50mΩ(10A)	17c	Nec	2SJ177, 2SJ294, 2SJ322
2SJ331	MOS-P-FET-e*	V-MOS, LogL, 60V, ±30A, 150W, <0,03Ω	18p	Nec	2SJ217
2SJ332(L,S)	MOS-P-FET-e*	V-MOS, LogL, 20V, 10A, 20W, <0,06Ω(5A)	30p	Hit	2SJ389
2SJ333(L,S)	MOS-P-FET-e*	V-MOS, LogL, 30V, 7A, 20W, <0,14Ω(4A)	30p	Hit	2SJ246
2SJ334	MOS-P-FET-e*	V-MOS, LogL, 60V, 30A, 45W, <38mΩ(15A)	17c	Tos	2SJ295
2SJ335	MOS-P-FET-e*	SMD, V-MOS, LogL, 12V, 0,5A, <14Ω	39b	Say	2SJ190, 2SJ278
2SJ336	MOS-P-FET-e*	V-MOS, LogL, 12V, 2A, 20W, <0,35Ω(1A)	30p	Say	2SJ191
2SJ337	MOS-P-FET-e*	V-MOS, LogL, 12V, 8A, 30W, <0,09Ω(4A)	30p	Say	2SJ246, 2SJ333
2SJ338	MOS-P-FET-e	V-MOS, 160V, 1A, 20W, <5Ω	30p	Tos	2SJ130
2SJ339	MOS-P-FET-e	V-MOS, LogL, 60V, 25A, 40W, <55mΩ(15A)	17c	Say	2SJ295, 2SJ323
2SJ340	MOS-P-FET-e	V-MOS, LogL, 60V, 30A, 70W, <40mΩ(15A)	30p	Say	2SJ280
2SJ341	MOS-P-FET-e*	V-MOS, LogL, 20V, 5A, 12W, <0,12Ω(3A)	14b	Hit	2SJ250, 2SJ300
2SJ342	MOS-P-FET-e*	V-MOS, int. Di(G→S), 50V, 0,05A, <50Ω	41f	Tos	—
2SJ343	MOS-P-FET-e*	=2SJ342: SMD	35a	Tos	—
2SJ344	MOS-P-FET-e*	=2SJ342: SMD	35a(2mm)	Tos	—
2SJ345	MOS-P-FET-e	V-MOS, int. Di(G→S), 20V, 0,05A, <40Ω	35a	Tos	—
2SJ346	MOS-P-FET-e	=2SJ345:	35a(2mm)	Tos	—
2SJ347	MOS-P-FET-e	=2SJ345:	35a(1,6mm)	Tos	—
2SJ348	MOS-P-FET-e	V-MOS, LogL, 60V, 30A, 70W, <0,04Ω(15A)	17p	Say	2SJ292
2SJ349	MOS-P-FET-e*	V-MOS, LogL, 60V, 20A, 35W, <45mΩ(10A)	17c	Tos	2SJ177, 2SJ294, 2SJ322
2SJ350	MOS-P-FET-e*	V-MOS, LogL, 120V, 8A, 20W, <0,7Ω(4A)	15c	Hit	—
2SJ351	MOS-P-FET-e*	V-MOS, NF-L, 160V, 8A, 100W, 320/120ns	18d	Hit	—
2SJ352	MOS-P-FET-e*	=2SJ351: 200V	18d	Hit	—
2SJ353	MOS-P-FET-e*	V-MOS, LogL, 60V, ±1,5A, 1W, <0,37Ω(1A)	9c	Nec	—
2SJ355	MOS-P-FET-e*	SMD, V-MOS, LogL, 30V, ±2A, <0,35Ω(1A)	39b	Nec	2SJ356
2SJ356	MOS-P-FET-e*	SMD, V-MOS, LogL, 60V, ±2A, <0,5Ω(1A)	39b	Nec	—
2SJ357	MOS-P-FET-e*	SMD, V-MOS, LogL, 30V, ±3A, <0,2Ω(1,5A)	39b	Nec	2SJ358
2SJ358	MOS-P-FET-e*	SMD, V-MOS, LogL, 60V, ±3A, <0,3Ω(1,5A)	39b	Nec	—
2SJ359	MOS-P-FET-e	V-MOS, LogL, 60V, 5A, <0,25Ω(2,5A)	≈12	Tos	—
2SJ380	MOS-P-FET-e	SMD, V-MOS, LogL, 60V, 1A, <0,73Ω(0,5A)	39b	Tos	2SJ190, 2SJ278
2SJ361	MOS-P-FET-e*	SMD, V-MOS, LogL, 20V, 2A, <0,4Ω(1A)	39j	Hit	—
2SJ361	MOS-P-FET-e*	integr. Rgate			—
2SJ362	MOS-P-FET-e	V-MOS, LogL, 60V, 2A, 20W, <0,4Ω(1A)	30p	Say	2SJ191, 2SJ194
2SJ363	MOS-P-FET-e*	SMD, V-MOS, LogL, 30V, 2A, <0,45Ω(1A)	39j	Hit	(2SJ355...356)
2SJ363	MOS-P-FET-e*	integr. Rgate			—
2SJ365	MOS-P-FET-e	V-MOS, 60V, 2A, 10W, <0,45Ω, 60/160ns	30p	Shi	2SJ191, 2SJ223
2SJ366	MOS-P-FET-e	V-MOS, 60V, 5A, 15W, <0,25Ω, 70/270ns	30p	Shi	2SJ192, 2SJ245, 2SJ279
2SJ387	MOS-P-FET-e	V-MOS, 60V, 5A, 30W, <0,25Ω, 70/270ns	30p	Shi	2SJ214
2SJ388	MOS-P-FET-e	=2SJ367: 20W	17c	Shi	2SJ248
2SJ369	MOS-P-FET-e	V-MOS, 60V, 10A, 40W, <0,16Ω, 100/320ns	30p	Shi	2SJ219, 2SJ296
2SJ370	MOS-P-FET-e	=2SJ369: 25W	17c	Shi	2SJ236, 2SJ293, 2SJ321
2SJ371	MOS-P-FET-e	V-MOS, 60V, 15A, 50W, <0,1Ω, 130/460ns	30p	Shi	2SJ219, 2SJ296
2SJ372	MOS-P-FET-e	=2SJ371:	17c	Shi	2SJ237, 2SJ293, 2SJ321
2SJ373	MOS-P-FET-e	V-MOS, 60V, 20A, 60W, <0,07Ω, 175/660ns	30p	Shi	2SJ220, 2SJ297
2SJ374	MOS-P-FET-e	=2SJ373:	17c	Shi	2SJ294, 2SJ322, 2SJ374
2SJ375	MOS-P-FET-e	V-MOS, 60V, 30A, 60W, <45mΩ, 270/1020ns	30p	Shi	—
2SJ376	MOS-P-FET-e	=2SJ375:	17c	Shi	2SJ295, 2SJ323
2SJ377	MOS-P-FET-e	V-MOS, LogL, 60V, 5A, 20W, <0,19Ω(2,5A)	30p	Tos	2SJ192, 2SJ245, 2SJ327
2SJ378	MOS-P-FET-e	=2SJ377: 1,2W	≈12		—
2SJ379	MOS-P-FET-e	V-MOS, LogL, 100V, 8A, 15W, <0,21Ω(4A)	≈30p	Tos	—
2SJ380	MOS-P-FET-e	V-MOS, LogL, 100V, 12A, 35W, <0,21Ω(6A)	17c	Tos	2SJ222
2SJ381	MOS-P-FET-e	SMD, V-MOS, LogL, 12V, 2A, <0,4Ω(0,5A)	39b	Say	2SJ355.356
2SJ382	MOS-P-FET-e	V-MOS, LogL, 12V, 4A, 20W, <177mΩ(1A)	30p	Say	2SJ192, 2SJ245, 2SJ327
2SJ383	MOS-P-FET-e	V-MOS, LogL, 12V, 8A, 30W, <82mΩ(2A)	30p	Say	2SJ389
2SJ384(L,S)	MOS-P-FET-e*	V-MOS, LogL, 60V, 15A, 50W, <0,1Ω(8A)	30p	Hit	2SJ268
2SJ386	MOS-P-FET-e*	V-MOS, LogL, 30V, 3A, 0,9W, <0,4Ω(2A)	7c	Hit	—

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2SJ387(L,S)	MOS-P-FET-e*	V-MOS, LogL, 20V, 10A, 20W, <70mΩ(5A)	79p	Hit	2SJ388..389
2SJ388(L,S)	MOS-P-FET-e*	V-MOS, LogL, 30V, 10A, 20W, <80mΩ(5A)	30p	Hit	2SJ389
2SJ389(L,S)	MOS-P-FET-e*	V-MOS, LogL, 60V, 10A, 30W, <135mΩ(5A)	30p	Hit	—
2SJ39	P-FET	Dual, 60V, Idss=112mA, Up<6V	7-SIP	Mit	—
2SJ390	MOS-P-FET-e*	V-MOS, LogL, 60V, 10A, 25W, <0,12Ω(5A)	17c	Hit	2SJ175..176, 2SJ236
2SJ399	MOS-P-FET-e*	SMD, V-MOS, LogL, 30V, 0,2A, <7Ω(10mA)	35a	Hit	—
2SJ399	MOS-P-FET-e*	integr. Rgate			—
2SJ40	P-FET	Analog-S, 50V, Idss=0,6..12mA, Up<6V	41a	Mit	—
2SJ400	MOS-P-FET-e	V-MOS, LogL, 30V, 35A, 70W, <35mΩ	30p	Say	2SJ280
2SJ401	MOS-P-FET-e	V-MOS, 20V, 20A, 100W, <45mΩ(10A)	30p	Tos	2SJ409
2SJ403	MOS-P-FET-e	V-MOS, LogL, 200V, 5A, 25W, <1,1Ω(2,5A)	17c	Say	2SJ320
2SJ404	MOS-P-FET-e	V-MOS, LogL, 200V, 6A, 25W, <0,8Ω(3A)	17c	Say	—
2SJ405	MOS-P-FET-e	V-MOS, LogL, 200V, 6A, 30W, <0,5Ω(4A)	17c	Say	—
2SJ406	MOS-P-FET-e	V-MOS, LogL, 200V, 12A, 40W, <0,23Ω	17c	Say	—
2SJ407	MOS-P-FET-e	V-MOS, 200V, 5A, 30W, <1Ω(2,5A)	17c	Tos	2SJ320
2SJ406(L,S)	MOS-P-FET-e*	V-MOS, LogL, 60V, 50A, 100W, <0,02Ω(25A)	30p	Hit	—
2SJ409(L,S)	MOS-P-FET-e*	V-MOS, LogL, 100V, 20A, 75W, <0,16Ω(10A)	79p	Hit	—
2SJ410(L,S)	MOS-P-FET-e*	V-MOS, 200V, 6A, 30W, <0,85Ω(3A)	15c	Hit	2SJ307..308
2SJ413	MOS-P-FET-e	V-MOS, LogL, 60V, 50A, 70W, <0,02Ω	18c	Say	2SJ218
2SJ414	MOS-P-FET-e	V-MOS, LogL, 60V, 15A, 50W, <0,08Ω(9A)		Say	—
2SJ415	MOS-P-FET-e	V-MOS, LogL, 60V, 6A, 40W, <0,15Ω(5A)		Say	—
2SJ416	MOS-P-FET-e	SMD, V-MOS, LogL, 30V, 2A, <0,44Ω(1A)	39b	Say	2SJ356
2SJ417	MOS-P-FET-e	SMD, V-MOS, LogL, 30V, 4A, 20W, <0,16Ω	30p	Say	2SJ192, 2SJ245, 2SJ279
2SJ418	MOS-P-FET-e	SMD, V-MOS, LogL, 30V, 6A, 30W, <0,06Ω	30p	Say	—
2SJ419	MOS-P-FET-e	SMD, V-MOS, LogL, 12V, 4A, <82mΩ(2A)	8-MDIP	Say	—
2SJ420	MOS-P-FET-e	SMD, V-MOS, LogL, 12V, 5A, <63mΩ(2,5A)	8-MDIP	Say	—
2SJ421	MOS-P-FET-e	SMD, V-MOS, LogL, 30V, 5A, <58mΩ(2A)	8-MDIP	Say	—
2SJ43	P-FET	Uni, 50V, Idss=0,5..12mA, Up<3V	7e	Mat	2SJ129
2SJ437	MOS-P-FET-e	V-MOS, 30V, 35A, 50W, <16mΩ		Say	—
2SJ44	P-FET	Uni, ra, 40V, Idss=118mA, Up<1,5V	7e	Nec	2N5021, 2SJ74
2SJ443	MOS-P-FET-e*	V-MOS, LogL, 60V, 10A, 25W, <0,18Ω(5A)	17c	Hit	2SJ175..176, 2SJ236, 2SJ390
2SJ45	P-FET	Uni, ra, 40V, Idss=118mA, Up<1,5V	7e	Nec	2N5021, 2SJ74
2SJ450	MOS-P-FET-e*	SMD, V-MOS, LogL, 60V, 1A, <1,2Ω(0,5A)	39j	Hit	2SJ190, 2SJ278
2SJ451	MOS-P-FET-e*	SMD, V-MOS, LogL, 20V, 0,2A, <3,5Ω(0,1A)	35a	Hit	—
2SJ451	MOS-P-FET-e*	integr. Rgate			—
2SJ452	MOS-P-FET-e*	SMD, V-MOS, LogL, 50V, 0,2A, <7Ω(0,1A)	35a	Hit	—
2SJ452	MOS-P-FET-e*	integr. Rgate			—
2SJ453	MOS-P-FET-e	V-MOS, LogL, 250V, 3A, 30W, <2,6Ω(1,5A)	30p	Say	2SJ281
2SJ454	MOS-P-FET-e	FREDFET, 250V, 5A, 40W, <1,3Ω(3A)		Say	—
2SJ455	MOS-P-FET-e	FREDFET, 250V, 7A, 45W, <0,9Ω(4A)		Say	—
2SJ456	MOS-P-FET-e	FREDFET, 250V, 9A, 50W, <0,82Ω(5A)		Say	—
2SJ457	MOS-P-FET-e	FREDFET, 450V, 0,5A, 30W, <15Ω(0,3A)	30p	Say	—
2SJ456	MOS-P-FET-e	FREDFET, 450V, 2A, 60W, <5,5Ω(1A)	30p	Say	—
2SJ459	MOS-P-FET-e	FREDFET, 450V, 4A, 70W, <2,8Ω(2A)	30p	Say	—
2SJ466	MOS-P-FET-e	V-MOS, LogL, 30V, 35A, 50W, <0,03Ω		Say	—
2SJ467	MOS-P-FET-e	V-MOS, LogL, 30V, 6A, 30W, <0,1Ω	30p	Say	—
2SJ468	MOS-P-FET-e	V-MOS, LogL, 30V, 4A, <0,1Ω	8-MDIP	Say	—
2SJ469	MOS-P-FET-e	V-MOS, LogL, 30V, 5A, <0,08Ω	8-MDIP	Say	—
2SJ47	MOS-P-FET-e	V-MOS, 100V, 7A, 100W, 25/24ns, <1,7Ω	23e	Hit	2SJ55..56, 2SJ160..162
2SJ471	MOS-P-FET-e*	V-MOS, LogL, 30V, 30A, 30W, <35mΩ(15A)	15c	Hit	2SJ295, 2SJ323
2SJ479	MOS-P-FET-e*	=2SJ471: 50W	79p	Hit	—
2SJ48	MOS-P-FET-e	=2SJ47: 120V	23e	Hit	2SJ55..56, 2SJ160..182
2SJ483	MOS-P-FET-e*	V-MOS, LogL, 30V, 5A, 0,9W, <0,11Ω(2,5A)	7c	Hit	—
2SJ484	MOS-P-FET-e*	SMD, V-MOS, LogL, 30V, 2A, <0,23Ω(1A)	39j	Hit	2SJ356
2SJ486	MOS-P-FET-e*	SMD, V-MOS, LogL, 30V, 0,3A, <0,65Ω	35a	Hit	—
2SJ486	MOS-P-FET-e*	integr. Rgate			—
2SJ49	MOS-P-FET-e	=2SJ47: 140V	23e	Hit	2SJ55..56, 2SJ161..182
2SJ50	MOS-P-FET-e	=2SJ47: 160V	23e	Hit	2SJ55..56, 2SJ182
2SJ51	P-FET	NF/S, ra, 40V, Idss=6..50mA, Up<1,1V	7e(9mm)	Hit	2SJ70
2SJ55	MOS-P-FET-e	V-MOS, 160V, 6A, 125W, <1,7Ω	23e	Hit	—
2SJ56	MOS-P-FET-e	=2SJ55: 200V	23e	Hit	—
2SJ68	P-FET	NF/S, ra, 40V, Idss=1,6..12mA, Up<1,5V	7a	Hit	2SJ104, 2SJ107..106
2SJ69	P-FET	NF/S, ra, 40V, Idss=2,5..20mA, Up<1,5V	7a	Hit	2SJ104, 2SJ107..106
2SJ70	P-FET	NF/S, ra, 40V, Idss=6..50mA, Up<1,5V	7a(9mm)	Hit	2SJ51
2SJ72	P-FET	Uni, 25V, Idss=5..30mA, Up<2V	7a(9mm)	Tos	2SJ110..111
2SJ73	P-FET	=2SJ72: gep	2x7a(9mm)	Tos	(2x2SJ110..111)

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2SJ74	P-FET	Uni, 25V, Idss>1mA, Up<2V	7a	Tos	2N5021
2SJ75	P-FET	=2SJ74: gep	2x7a	Tos	(2x2N5021)
2SJ76	MOS-P-FET-e*	V-MOS, 140V, 0,5A, 30W, 20/30ns, 10Ω	17d	Hit	—
2SJ77	MOS-P-FET-e*	=2SJ76: 160V	17d	Hit	—
2SJ78	MOS-P-FET-e*	=2SJ76: 160V	17d	Hit	—
2SJ79	MOS-P-FET-e*	=2SJ76: 200V	17d	Hit	—
2SJ81	MOS-P-FET-e	V-MOS, 120V, 7A, 100W, <1,7Ω, 230/110ns	20d	Hit	(2SJ99..100)
2SJ82	MOS-P-FET-e	=2SJ81: 140V	20d	Hit	(2SJ99..100)
2SJ83	MOS-P-FET-e	=2SJ81: 160V	20d	Hit	(2SJ100)
2SJ84	P-FET	SMD, Uni, 15V, Idss=0,5..12mA, Up<3V	35f	Mat	—
2SJ85	MOS-P-FET-e	→2SJ76		Hit	—
2SJ86	MOS-P-FET-e	→2SJ76		Hit	—
2SJ87	MOS-P-FET-e	→2SJ76		Hit	—
2SJ90	P-FET	Dual, 30V, Idss=2,6..20mA, Up>2V	7-SIP	Tos	—
2SJ91	MOS-P-FET-e	V-MOS-L, 140V, 8A, 120W	23a	Tos	2SJ114..115, 2SJ118..119, (2SJ55..56)
2SJ92	MOS-P-FET-e	=2SJ91: 7A, 100W	18p	Tos	2SJ114..115, 2SJ118..119
2SJ96	MOS-P-FET-e	V-MOS, 60V, 8A, 100W, <0,8Ω, 100/250ns	20d	Hit	2SJ81..83, (2SJ99..100)
2SJ99	MOS-P-FET-e	V-MOS, 140V, 8A, 100W, <0,5Ω, 100/90ns	20p	Hit	(2SJ82..83)
2SK					2SK
2SK1000	N-FET	AM-Tuner, 22V, 50mA, Idss>10mA, Up<2,5V	40a	Nec	—
2SK1001	N-FET	=2SK1000: SMD	35f	Nec	—
2SK1002	N-FET	Mikrof, 20V, Idss=0,12..0,5mA, Up<1V	40a	Nec	—
2SK1006	MOS-N-FET-e	V-MOS, S-L, 450V, 5A, 40W, <1,6Ω(2,5A)	≈15c	Fjd	2SK1231..32, 2SK1351, 2SK1608, 2SK1626++
2SK1007	MOS-N-FET-e	=2SK1006: 60W	17p	Fjd	BUZ41A..42, 2SK893, 2SK1156, 2SK1246,++
2SK1006	MOS-N-FET-e	=2SK1008: 500V, 4,5A, 60W, <2,2Ω(2,5A)	17p	Fjd	BUZ41A..42, 2SK893, 2SK1158, 2SK1246,++
2SK1009	MOS-N-FET-e	V-MOS, S-Reg, 450V, 7A, 60W, <1,3Ω(3A)	17p	Fjd	IRF840, IRF842, 2SK894, 2SK1495..98,++
2SK1010	MOS-N-FET-e	=2SK1009: 500V, 8A, <1,6Ω(3A)	17p	Fjd	IRF840, IRF842, 2SK894, 2SK1496,++
2SK1011	MOS-N-FET-e	V-MOS, S-Reg, 450V, 10A, 100W, <0,65Ω	18p	Fjd	BUZ339, 2SK896, 2SK1488, 2SK1785,++
2SK1012	MOS-N-FET-e	=2SK1011: 500V, <0,9Ω(5A)	18p	Fjd	BUZ339, 2SK896, 2SK1488, 2SK1785,++
2SK1013	MOS-N-FET-e	V-MOS, S-Reg, 450V, 13A, 125W, <0,6Ω(6A)	18p	Fjd	2SK899, 2SK1610, 2SK1745, 2SK1757,++
2SK1014	MOS-N-FET-e	=2SK1013: 500V, 12A, <0,74Ω(6A)	18p	Fjd	2SK899, 2SK1610, 2SK1745, 2SK1757,++
2SK1015	MOS-N-FET-e	V-MOS, S-Reg, 450V, 18A, 125W, <0,45Ω(8A)	18p	Fjd	2SK870, 2SK1517..18, 2SK1499..1500,++
2SK1016	MOS-N-FET-e	=2SK1015: 500V, 15A, <0,55Ω(8A)	18p	Fjd	2SK899, 2SK1745, 2SK1678, 2SK1757,++
2SK1017	MOS-N-FET-e	V-MOS, S-Reg, 450V, 20A, 150W, <0,35Ω	18p	Fjd	2SK870, 2SK1517..18, 2SK1409, 2SK1680,++
2SK1018	MOS-P-FET-e	=2SK1017: 500V, 18A, <0,45Ω(10A)	18p	Fjd	2SK870, 2SK1518, 2SK1498, 2SK1680,++
2SK1019	MOS-N-FET-e	V-MOS, S-Reg, 450V, 35A, 300W, <0,2Ω	77p	Fjd	2SK1519..20, 2SK1828..29
2SK1020	MOS-N-FET-e	=2SK1019: 500V, 30A, <0,25Ω(15A)	77p	Fjd	2SK1520, 2SK1629
2SK1021	MOS-N-FET-e	V-MOS, S-Reg, 800V, 3A, 60W, <6Ω(1,5A)	17p	Fjd	BUZ81, 2SK1501, 2SK1639, 2SK1843, ++
2SK1022	MOS-N-FET-e	=2SK1021: 900V, 2,5A, <7,3Ω(1,5A)	17p	Fjd	BUK456-1000, 2SK791..92, 2SK1793, ++
2SK1023	MOS-N-FET-e	V-MOS, S-Reg, 600V, 4A, 60W, <4,5Ω(2A)	17p	Fjd	BUZ81, 2SK1501, 2SK1639, 2SK1643,++
2SK1024	MOS-N-FET-e	=2SK1023: 900V, 3,5A	17p	Fjd	2SK1457, 2SK1501, 2SK1839, 2SK1643,++
2SK1025	MOS-N-FET-e	V-MOS, S-L, 50V, 20A, 45W, <0,08Ω(10A)	17c	Mit	BUK445-50, BUZ11F, 2SK1095, 2SK1420,++
2SK1026	MOS-N-FET-e	V-MOS, S-L, 250V, 20A, 150W, <0,26Ω	≈18p	Mit	2SK901, 2SK944, 2SK1641, 2SK1673..74, ++
2SK1027	MOS-N-FET-e	=2SK1026: 300V, <0,29Ω(10A)	≈18p	Mit	2SK1409, 2SK1674, 2SK1680
2SK1026	MOS-N-FET-e	V-MOS, VHF-L, PQ=100W(230MHz)	61	Tos	—
2SK1026	MOS-N-FET-e	V-MOS, DC-DC, 500V, ±10A, 200W, <0,5Ω	77p	Tos	2SK694
2SK103	N-FET	NF/HF-V, 20V, Idss=0,02..1mA, Up<0,8V		Nec	—
2SK1030	MOS-N-FET-e	V-MOS, S-L, 800V, 3A, 50W, <5Ω(2A)	17c	Mat	2SK1356, 2SK1460
2SK1030A	MOS-N-FET-e	=2SK1030: 900V	17c		2SK1356, 2SK1460
2SK1031	N-FET	SMD, NF, 50V, 10mA, Idss>0,6mA, Up<5V	35f	Hit	—
2SK1032	MOS-N-FET-e	V-MOS, S-L, 800V, 8A, 120W, <1,7Ω(5A)	18p	Mat	2SK884, 2SK1342, 2SK1358, 2SK1502, ++
2SK1032A	MOS-N-FET-e	=2SK1032: 900V	18p		2SK1342, 2SK1358, 2SK1462, 2SK1614, ++
2SK1033	MOS-N-FET-e	V-MOS, LogL, 60V, 12A, 45W, <0,1Ω(6A)	17c	Mat	2SK1093, 2SK1256, 2SK1305..06, 2SK1344++
2SK1034	MOS-N-FET-e	V-MOS, LogL, 100V, 15A, 45W, <0,18Ω(6A)	17c	Mat	2SK1306, 2SK1558
2SK1035	MOS-N-FET-e	V-MOS, LogL, 150V, 12A, 45W, <0,35(6A)	17c	Mat	—
2SK1036	MOS-N-FET-e	V-MOS, 250V, 10A, 50W, <0,3Ω(5A)	17c	Mat	2SK526
2SK1037	MOS-N-FET-e	V-MOS, 250V, 50W	17c	Mat	—
2SK1036	MOS-N-FET-e	V-MOS, S-L, 400V, 5A, 50W, <1,8Ω(3A)	17c	Mat	BUK445-400, 2SK530, 2SK1377, 2SK1990,++
2SK1039	MOS-N-FET-e	V-MOS, S-L, 400V, 8A, 50W, <1,4Ω(5A)	17c	Mat	2SK1566..67, 2SK1609, 2SK2116..17,++
2SK104	N-FET	Uni, 30V, Idss=0,5..12mA, Up<4,5V	7f	Nec	BFS70, 2N3921, 2N4220, 2N5359, 2SK104++,
2SK1040	MOS-P-FET-e	V-MOS, S-L, 400V, 10A, 100W, <1Ω(5A)	16c(p)	Mat	BUZ326, BUZ351, 2SK556, 2SK634
2SK1041	MOS-N-FET-e	V-MOS, S-L, 400V, 15A, 120W, <0,55Ω		Mat	BUK837-400, BUZ323
2SK1042	MOS-N-FET-e	V-MOS, S-L, 400V, 20A, 150W, <0,45Ω		Mat	2SK968
2SK1043	GaAs-N-FET-d	UHF, X..K-Band, 4V, Idss=12..60mA, 12G	51(SGSD)	Nec	—
2SK1044	MOS-N-FET-e	V-MOS, S-L, 800V, 5A, 150W, <1,7Ω(2,5A)	≈16c	Mit	2SK727, 2SK793, 2SK1461, 2SK1849..50,++
2SK1045	MOS-N-FET-e	=2SK1044: 900V, <2Ω(2,5A)	≈18c	Mit	2SK727, 2SK794, 2SK1341, 2SK1849..50, ++

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2SK1046	GaAs-N-FET-d	UHF, C..K-Band, 4V, 70mA, 12GHz	51(SGSD)	Nec	—
2SK1047	MOS-N-FET-e	V-MOS, S-L, 250V, 20A, 150W, <0,26Ω	≈18c	Mit	2SK901, 2SK944, 2SK1673..74, 2SK1641
2SK1048	MOS-N-FET-e	=2SK1047: 300V, <0,29Ω(10A)	≈18c	Mit	2SK868(A), 2SK1674
2SK1049	MOS-N-FET-e	V-MOS, S-L, 450V, 15A, 150W, <0,65Ω(8A)	≈18c	Mit	2SK899, 2SK1610, 2SK1678, 2SK1745, ++
2SK105	N-FET	=2SK104: 50V	7a	Nec	—
2SK1050	MOS-N-FET-e	=2SK1049: 500V, <0,78Ω(8A)	≈18c	Mit	2SK899, 2SK1610, 2SK1678, 2SK1745, ++
2SK1051	MOS-N-FET-e	V-MOS, S-L, 50V, 40A, 120W, <0,03Ω(20A)	≈18c	Mit	BUZ347..348, 2SK857, 2SK905, 2SK1124, +
2SK1052	MOS-N-FET-e	V-MOS, L, 450V, 0,5A, 30W, <7Ω(0,3A)	17p	Say	—
2SK1053	MOS-N-FET-e	V-MOS, L, 450V, 1A, 40W, <4,5Ω(0,5A)	17p	Say	—
2SK1056	MOS-N-FET-e*	V-MOS, 120V, 7A, 100W, 180/60ns	18d,p(?)	Hit	(2SK405, 2SK413..414)
2SK1057	MOS-N-FET-e*	=2SK1056: 140V	18d	Hit	(2SK405, 2SK413..414)
2SK1056	MOS-N-FET-e*	=2SK1056: 160V	18d	Hit	(2SK400)
2SK1059(Z)	MOS-N-FET-e	V-MOS, S-L, 60V, ±5A, 20W, <0,135Ω(3A)	30p	Nec	2SK1112, 2SK1471, 2SK1719
2SK106	N-FET	Uni, 50V, Idss=0,5..12mA, Up<1,5V	7a	Hit	2SK66, 2SK121, 2SK163, 2SK170, 2SK184
2SK1060(Z)	MOS-N-FET-e	=2SK1059: 100V, <0,27Ω(3A)	30p	Nec	2SK1474, 2SK1804
2SK1061	MOS-N-FET-e	=2SK982: 0,3W	41c	Tos	BS170, BST170, 2SK422..423
2SK1062	MOS-N-FET-e	=2SK982: SMD	35a	Tos	BST82
2SK1063	MOS-N-FET-e*	=2SK559: 125W	23a	Hit	2SK788, 2SK899, 2SK1610, 2SK1678, ++
2SK1064	MOS-N-FET-e*	=2SK560: 125W	23a	Hit	2SK788, 2SK899, 2SK1610, 2SK1678, ++
2SK1065	N-FET	=2SK988:	35e(2mm)	Say	—
2SK1066	MOS-N-FET	=2SK436:	85f(2mm)	Say	—
2SK1067	MOS-N-FET-d	=2SK543:	35e(2mm)	Say	—
2SK1068	N-FET	=2SK546: SMD	35f(2mm)	Say	—
2SK1069	N-FET	=2SK771: SMD	35f(2mm)	Say	—
2SK107	N-FET	FM/VHF, 27V, Idss>2,7mA, Up<3,85V	7e	Sor	BF410B, 2SK192
2SK1070	N-FET	=2SK435: SMD	35f	Hit	—
2SK1073	MOS-N-FET-e	=2SK1074: Iso, 45W	17c	Mit	2SK1356, 2SK1460
2SK1074	MOS-N-FET-e	V-MOS, S-L, 800V, 3A, 120W, <3,6Ω(1,5A)	≈18p	Mit	2SK603, 2SK726, 2SK954, 2SK1339
2SK1078	MOS-N-FET-e	=2SK940: SMD	39b	Tos	2SK1697, 2SK1727, 2SK2109
2SK1079	MOS-N-FET-e	=2SK941: SMD	39b	Tos	2SK1079, 2SK1485, 2SK1728
2SK108	N-FET	Uni, ra, 50V, Idss=1..12mA, Up<3V	7e	Mit	BF410B, BFW12, 2N4340, 2N5484, ++
2SK1081	MOS-N-FET-e	V-MOS, S-Reg, 800V, 7A, 125W, <2,2Ω(3A)	18p	Fjd	BUK638-800, 2SK884, 2SK1032, 2SK1502, ++
2SK1082	MOS-N-FET-e	=2SK1081: 6A, <2,8Ω(3A)	18p	Fjd	BUK638-800, 2SK684, 2SK1032, 2SK1502, ++
2SK1083	MOS-N-FET-e	V-MOS, S-L, 60V, 8A, 20W, <0,22Ω(4A)	≈15c	Fjd	BUK542-60, 2SK1261, 2SK1556
2SK1084	MOS-N-FET-e	V-MOS, S-L, 100V, 5A, 20W, <0,5Ω(2,5A)	≈15c	Fjd	BUK542-100, 2SK1260, 2SK1265
2SK1085	MOS-N-FET-e	V-MOS, S-L, 150V, 3A, 20W, <0,9Ω(1,5A)	≈15c	Fjd	2SK1264..1265
2SK1086	MOS-N-FET-e	V-MOS, S-L, 60V, 20A, 35W, <0,07Ω(10A)	≈15c	Fjd	2SK943, 2SK1214, 2SK1345, 2SK1951, ++
2SK1087	MOS-N-FET-e	V-MOS, S-L, 100V, 12A, 35W, <0,17Ω(8A)	≈15c	Fjd	2SK1034, 2SK1306, 2SK1556
2SK1088	MOS-N-FET-e	V-MOS, S-L, 150V, 9A, 35W, <0,13Ω(4,5A)	≈15c	Fjd	BUK545-200, 2SK1035
2SK1089	MOS-N-FET-e	V-MOS, S-L, 60V, 35A, 80W, <0,035Ω	18p	Fjd	2SK1297, 2SK1514, 2SK1665
2SK109(A)	N-FET	=2SK106: Dual	7-SIP	Mit	—
2SK1090	MOS-N-FET-e	V-MOS, S-L, 100V, 20A, 80W, <0,06Ω(10A)	18p	Fjd	2SK1267
2SK1091	MOS-N-FET-e	V-MOS, S-L, 150V, 15A, 80W, <0,15Ω	18p	Fjd	2SK1267
2SK1092	GaAs-N-FET	=2SK666: SMD	44(SD-G)	Hit	—
2SK1093	MOS-N-FET-e*	=2SK970: Iso, 20W	17c	Hit	2SK1033, 2SK1256, 2SK1305..06, 2SK1344
2SK1094	MOS-N-FET-e*	=2SK971: Iso, 25W	17c	Hit	2SK1034, 2SK1306, 2SK1345, 2SK1558
2SK1095	MOS-N-FET-e*	=2SK972: Iso, 30W	17c	Hit	2SK94S, 2SK1S45..4S, 2SK1S48..49
2SK1096	MOS-N-FET-e	V-MOS, S-L, 60V, 13A, 30W, <0,12Ω(7A)	≈15c	Fjd	2SK10S4, 2SK1S06, 2SK155S
2SK1097	MOS-N-FET-e	V-MOS, S-L, 100V, 8A, 30W, <0,2SΩ(4A)	≈15c	Fjd	BUK543-100, 2SK1261, 2SK1556
2SK1098	MOS-N-FET-e	V-MOS, S-L, 150V, 8A, 30W, <0,5Ω(SA)	≈15c	Fjd	BUK545-200
2SK1099	MOS-N-FET-e	V-MOS, S-L, 500V, 10A, 80W, <0,67Ω(5A)	18c(p)	Fjd	2SK1206, 2SK1523, 2SK1696, 2SK1832
2SK11	N-FET	Uni, 20V, Idss=0,3..6,5mA, Up<6V	5n	Tos	BFS70, 2N3369, 2N3821, 2SK381, ++
2SK110	N-FET	Uni, ra, 30V, 50mA, Idss>2,5mA, Up<2V	7a(9mm)	Mit	BC264A..D, BF410B..D, 2SK192, ++
2SK1100	GaAs-N-FET	UHF, Ku-Band, 4V, 60mA, 12GHz	51(SGSD)	Mat	—
2SK1101	MOS-N-FET-e	V-MOS, S-L, 450V, 10A, 50W, <0,65Ω(5A)	≈15c	Fjd	—
2SK1102	MOS-N-FET-e	=2SK1101: 500V, <0,9Ω(5A)	≈15c	Fjd	—
2SK1103	N-FET	=2SK1104: SMD	35f	Mat	—
2SK1104	N-FET	65V, 20mA, Idss=0,2..6mA, Up<3,5V	40a	Mat	—
2SK1105	MOS-N-FET-e	V-MOS, S-Reg, 800V, 3A, 80W, <0,4Ω(1,5A)	18c(p)	Fjd	BUZ307, BUZ360..61, 2SK603, 2SK1339
2SK1108	N-FET	C-Mikrofon-V, 20V, 10mA, Idss>0,04mA	40a	Nec	—
2SK1109	N-FET	=2SK110S: SMD	≈35b	Nec	—
2SK111	N-FET	=2SK110: Dual	7-SIP	Mit	—
2SK1112	MOS-N-FET-e	V-MOS, LogL, 60V, 5A, 20W, <0,16Ω	30p	Tos	2SK1471, 2SK1719, 2SK1949
2SK1113	MOS-N-FET-e	V-MOS, LogL, 120V, SA, 20W, <0,42Ω	30p	Tos	2SK1474
2SK1114	MOS-N-FET-e	V-MOS, LogL, 60V, 12A, 40W, <0,07Ω(8A)	17p	Tos	BUK552-60, 2SK970..971, 2SK1300
2SK1115	MOS-N-FET-e	V-MOS, LogL, 60V, 20A, 60W, <0,055Ω	17p	Tos	2SK942, 2SK972, 2SK1287

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2SK1116	MOS-N-FET-e	V-MOS, LogL, 100V, 25A, 100W, <0,055Ω	17p	Tos	BUK555-100, 2SK1347, 2SK1293
2SK1117	MOS-N-FET-e	V-MOS, S-Reg, 600V, 6A, 100W,	17p	Tos	BUZ90, 2SK1402, 2SK1501, 2SK1639, 2SK1643
2SK1118	MOS-N-FET-e	=2SK1117: Iso, 45W	17c	Tos	2SK1404, 2SK1637, 2SK2044
2SK1119	MOS-N-FET-e	V-MOS, SMPS(240V≈), 1000V, 4A, 100W	17p	Tos	—
2SK112	N-FET	Uni, ra, 50V, Idss>1,2mA, Up<1,2V	2b(G=case)	Tos	—
2SK1120	MOS-N-FET-e	V-MOS, SMPS(240V≈), 1000V, 8A, 150W	18p	Tos	2SK1954
2SK1121	MOS-N-FET-e	V-MOS, S-L, 50V, 25A, 45W, <0,03Ω(13A)	7c	Mit	BUK545-50, 2SK943, 2SK1345
2SK1122	MOS-N-FET-e*	V-MOS, LogL, 100V, ±40A, 100W, <50mΩ	18p	Nec	2SK1263, 2SK1304
2SK1123	MOS-N-FET-e*	V-MOS, LogL, 60V, ±40A, 100W, <27mΩ	18p	Nec	2SK1297, 2SK1514, 2SK1665
2SK1124	MOS-N-FET-e	V-MOS, 60V, 45A, 125W, <0,03Ω(25A)	18p	Tos	BUK439-60, 2SK849, 2SK857, 2SK1379, ++
2SK113	N-FET	Uni, 50V, Idss=5..150mA, Up<10V	2b(G=case)	Tos	—
2SK1131	N-FET	Uni, 20V, Idss=0,15..0,8mA	41e	Say	—
2SK1132	MOS-N-FET-e*	V-MOS, 50V, ±0,1A, 0,25W, <50Ω(20mA)	40c	Nec	BSS100
2SK1133	MOS-N-FET-e*	=2SK1132: SMD	35a	Nec	BSS123
2SK1134	MOS-N-FET-e	V-MOS, DC-DC, 50V, 45A, 80W, <0,03Ω	18c(p)	Fjd	BUZ347, 2SK905, 2SK1379, 2SK1514, ++
2SK1135	MOS-N-FET-e*	V-MOS, 250V, 15A, 100W, <0,22Ω(8A)	18p	Hit	2SK1401
2SK1136	MOS-N-FET-e	V-MOS, S-L, 50V, 10A, 30W, <0,06Ω(5A)	17c	Mit	BUK543-50, 2SK1256, 2SK1344
2SK1137	MOS-N-FET-e	V-MOS, S-L, 50V, 16A, 40W, <0,035Ω(8A)	17c	Mit	BUK545-50, 2SK943, 2SK1214, 2SK1345..46
2SK1136	MOS-N-FET-e	V-MOS, S-L, 150V, 7A, 30W, <0,3Ω(4A)	17c	Mit	BUK545-200
2SK1139	MOS-N-FET-e	V-MOS, S-L, 150V, 13A, 40W, <0,08Ω(7A)	17c	Mit	2SK1266
2SK1142	MOS-N-FET-e	V-MOS, S-L, 800V, 2A, 35W, <5Ω(1A)	17c	Mit	BUK446-800, 2SK1611, 2SK1834, 2SK1459
2SK1143	MOS-N-FET-e	=2SK1142: 900V, <6Ω(1A)	17c	Mit	2SK1459, 2SK1275
2SK1149	MOS-N-FET-e*	V-MOS, LogL, 100V, ±40A, 75W, <50mΩ(20A)	18c	Nec	—
2SK1150	MOS-N-FET-e*	V-MOS, LogL, 60V, ±40A, 75W, <27mΩ(20A)	18c	Nec	2SK1298, 2SK1666
2SK1151(L,S)	MOS-N-FET-e*	V-MOS, 450V, 1,5A, 20W, <5,5Ω(1A)	72p	Hit	2SK579..60, 2SK1327, 2SK1672
2SK1152(L,S)	MOS-N-FET-e*	=2SK1151: 500V, <6Ω(1A)	72p	Hit	2SK560, 2SK1327, 2SK1672
2SK1153	MOS-N-FET-e*	V-MOS, 450V, 3A, 30W, <2,8Ω(2A)	17c	Hit	BUZ41A..42, 2SK1244, 2SK1493..94
2SK1154	MOS-N-FET-e*	=2SK115: 3500V, <3Ω(2A)	17c	Hit	BUZ41A..42, 2SK1244, 2SK1494
2SK1155	MOS-N-FET-e*	V-MOS, 450V, 5A, 50W, <1,4Ω(2,5A)	17c	Hit	BUZ41A..42, IRF830, 2SK893, 2SK1246, ++
2SK1156	MOS-N-FET-e*	=2SK1155: 500V, <1,5Ω(2,5A)	17c	Hit	BUZ41A..42, IRF830, 2SK893, 2SK1246, ++
2SK1157	MOS-N-FET-e*	V-MOS, 450V, 7A, 60W, <0,8Ω(4A)	17c	Hit	IRF840, 2SK894, 2SK1495..96, 2SK1574, ++
2SK1158	MOS-N-FET-e*	=2SK1157: 500V, <0,9Ω(4A)	17c	Hit	IRF840, 2SK894, 2SK1496, 2SK1574, ++
2SK1159	MOS-N-FET-e*	V-MOS, 450V, 8A, 60W, <0,7Ω(4A)	17c	Hit	IRF840, 2SK894, 2SK1495..96, 2SK1574, ++
2SK1160	MOS-N-FET-e*	=2SK1159: 500V, <0,8Ω(4A)	17c	Hit	IRF840, 2SK894, 2SK1496, 2SK1574, ++
2SK1161	MOS-N-FET-e*	V-MOS, 450V, 10A, 100W, <0,8Ω(5A)	16c	Hit	2SK724, 2SK896, 2SK1488, 2SK1752, ++
2SK1162	MOS-N-FET-e*	=2SK1161: 500V, <0,9Ω(5A)	16c	Hit	2SK724, 2SK896, 2SK1488, 2SK1756, ++
2SK1163	MOS-N-FET-e*	V-MOS, 450V, 11A, 100W, <0,7Ω(5A)	16c	Hit	2SK724, 2SK896, 2SK1488, 2SK1752, ++
2SK1164	MOS-N-FET-e*	=2SK1163: 500V, <0,8Ω(5A)	16c	Hit	2SK724, 2SK896, 2SK1488, 2SK1753, ++
2SK1165	MOS-N-FET-e*	V-MOS, 450V, 12A, 100W, <0,55Ω(6A)	18c	Hit	2SK725, 2SK788, 2SK899, 2SK1610, 2SK1745
2SK1188	MOS-N-FET-e*	=2SK1165: 500V, <0,6(6A)	18c	Hit	2SK725, 2SK788, 2SK899, 2SK1610, 2SK1745
2SK1167	MOS-N-FET-e*	V-MOS, 450V, 15A, 100W, <0,36Ω(8A)	18c	Hit	2SK725, 2SK788, 2SK899, 2SK1610, 2SK1745
2SK1168	MOS-N-FET-e*	=2SK1167: 500V, <0,4Ω(8A)	18c	Hit	2SK725, 2SK788, 2SK899, 2SK1610, 2SK1745
2SK1169	MOS-N-FET-e*	V-MOS, 450V, 20A, 120W, <0,25Ω(10A)	18c	Hit	2SK870, 2SK1409, 2SK1411, 2SK1497..1500+
2SK117	N-FET	NF, ra, 50V, Idss>0,6mA, Up<1,5V	16c	Tos	2SK68, 2SK106, 2SK121, 2SK183, 2SK184, ++
2SK1170	MOS-N-FET-e*	=2SK1169: 500V, <0,27Ω(10A)	18p	Hit	2SK870, 2SK1411, 2SK1498, 2SK1500, ++
2SK1171	MOS-N-FET-e	V-MOS, S-L, 800V, 4A, 80W, <4,5Ω(2A)	18p	Fjd	2SK695, 2SK727, 2SK793..94, 2SK1649..50+
2SK1172	MOS-N-FET-e	=2SK1171: 900V, 3,5A, <5,5Ω(2A)	18p	Fjd	2SK794, 2SK1341, 2SK1649..50, 2SK1760
2SK1173	MOS-N-FET-e	50V, 0,5A, 0,2W		Mat	—
2SK1174	MOS-N-FET-e	V-MOS, S-L, 900V, 2,5A, 40W, <4Ω	17c	Sak	2SK1459
2SK1175	MOS-N-FET-e	V-MOS, S-L, 900V, 4,5A, 85W, <2,5Ω	18c	Sak	2SK809A, 2SK1463, 2SK1684
2SK1176	MOS-N-FET-e	V-MOS, S-L, 900V, 6,5A, 85W, <1,6Ω	18c	Sak	2SK1464, 2SK1685
2SK1177	MOS-N-FET-e	V-MOS, 500V, 2,5A, 30W, <3Ω	17c	Sak	BUK444-500, 2SK1756
2SK1178	MOS-N-FET-e	V-MOS, 500V, 4A, 35W, <1,5Ω	17c	Sak	2SK1232, 2SK1627
2SK1179	MOS-N-FET-e	V-MOS, 500V, 8,5A, 85W, <0,85Ω	18c	Sek	2SK1329, 2SK1523, 2SK1696
2SK118	N-FET	Uni, 50V, Idss>0,3mA, Up<1,5V	41e	Tos	2SK68, 2SK106, 2SK184
2SK1160	MOS-N-FET-e	V-MOS, 500V, 10A, 85W, <0,6Ω	18c	Sak	2SK1329, 2SK1523, 2SK1696
2SK1181	MOS-N-FET-e	V-MOS, 500V, 13A, 85W, <0,4Ω	18c	Sak	2SK1269, 2SK1524
2SK1182	MOS-N-FET-e	V-MOS, 500V, 18A, 90W, <0,27Ω	18c	Sak	2SK1269, 2SK1524
2SK1183	MOS-N-FET-e	V-MOS, 200V, 3A, 25W, <1,5Ω	17c	Sak	—
2SK1184	MOS-N-FET-e	V-MOS, 200V, 5A, 30W, <0,8Ω	17c	Sak	BUZ73(A)F
2SK1185	MOS-N-FET-a	V-MOS, 100V, 5A, 25W, <0,54Ω	17c	Sak	BUK442-100, BUK542-100, 2SK1260
2SK1186	MOS-N-FET-e	V-MOS, 100V, 9A, 30W, <0,27Ω	17c	Sak	BUK443-100, BUK543-100, 2SK1430, ++
2SK1187	MOS-N-FET-e	V-MOS, 100V, 12A, 35W, <0,16Ω	17c	Sak	BUK545-100, 2SK1430..31, 2SK1558, ++
2SK1188	MOS-N-FET-e	V-MOS, 60V, 10A, 25W, <0,2Ω	17c	Sak	BUK442-60, 2SK1033, 2SK1093
2SK1189	MOS-N-FET-e	V-MOS, 60V, 15A, 30W, <0,1Ω	17c	Sak	BUK445-60, 2SK1094, 2SK1419
2SK119	N-FET	Uni, 30V, 20mA, Idss>0,5mA, Up<4,5V	2a(G=case)	Nec	BFS70, 2N3821, 2N4220, 2N5359, 2SK104++

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2SK1190	MOS-N-FET-e	V-MOS, 60V, 22A, 35W, <0,05Ω	17c	Sak	BUK445-60, 2SK1095, 2SK1420
2SK1191	MOS-N-FET-e	V-MOS, 60V, 30A, 40W, <0,08Ω	17c	Sak	2SK1257, 2SK1421, 2SK1653
2SK1192	MOS-N-FET-e	V-MOS, 60V, 40A, 90W, <28mΩ	18c	Sak	2SK1298, 2SK1424, 2SK1666
2SK1193	MOS-N-FET-e	V-MOS, 60V, 45A, 95W, <20mΩ	18c	Sak	2SK1298, 2SK1424, 2SK1666
2SK1194	MOS-N-FET-e	V-MOS, S-L, 230V, 0,5A, 6W, <6Ω(0,5A)	30c	Shi	2SK1638
2SK1195	MOS-N-FET-e	V-MOS, S-L, 230V, 1,5A, 10W, <2Ω(1A)	30c	Shi	2SK375, 2SK535, 2SK945, 2SK1838
2SK1196	GaAs-N-FET	UHF, 6V, 70mA, Idss=20..70mA, 12GHz	51(SGSD)	Mat	—
2SK1197	MOS-N-FET-e*	V-MOS, HF-E, 100V, 0,5A, 20W, <50Ω	14c	Hit	—
2SK1196	MOS-N-FET-e	V-MOS, S-L, 700V, ±2A, 35W, <3,2Ω(1A)	17c	Nec	BUK448-800, 2SK1459, 2SK1611, 2SK1834++
2SK1199	MOS-N-FET-e*	V-MOS, 900V, 2A, 50W, <7Ω(1A), 70/125ns	17p	Hit	BUZ50, 2SK1324, 2SK1338
2SK12	N-FET	Uni, ra, 20V, Idss=0,45..5mA, Up<4,5V	5n	Tos	BFS70, 2N3821, 2N4220, 2SK104, ++
2SK120	N-FET	FM/VHF, 15V, 15mA, Idss>1mA, Up>0,3V	7f	Son	BF410A..B, 2N5484, 2SK192
2SK1200	MOS-N-FET-e*	V-MOS, 900V, 3A, 60W, <7Ω(1,5A)	18p	Hit	2SK726, 2SK794, 2SK1339, 2SK1341
2SK1201	MOS-N-FET-e*	V-MOS, 900V, 4A, 80W, <5,5Ω(2A)	18p	Hit	BUZ357..358, 2SK727, 2SK1341, 2SK1780++
2SK1202	MOS-N-FET-e*	V-MOS, 900V, 5A, 100W, <4Ω(3A)	16p	Hit	BUZ357..358, 2SK727, 2SK1341, 2SK1760++
2SK1203	MOS-N-FET-e*	V-MOS, 900V, 6A, 100W, <3Ω(3A)	18p	Hit	2SK1342, 2SK1358, 2SK1502, 2SK1614, ++
2SK1204	MOS-N-FET-e*	V-MOS, 900V, 6A, 100W, <1,8Ω(4A)	16p	Hit	2SK1342, 2SK1358, 2SK1502, 2SK1614 ++
2SK1205	MOS-N-FET-e*	V-MOS, 1000V, 5A, 100W, <2Ω(3A)	18p	Hit	BUZ357..358, 2SK665, 2SK1359
2SK1206	MOS-N-FET-e*	=2SK557: Iso, 60W	≈18c	Hit	2SK1331, 2SK1523..24
2SK121	N-FET	Uni, ra, 30V, Idss>0,9mA, Up<1,49V	7a, 7e	Son	BF410AB, 2N4340, 2SK163, 2SK170, ++
2SK1211	MOS-N-FET-e	V-MOS, S-L, 800V, 2,5A, 40W, <7Ω(1A)	17p	Fjd	BUZ60, 2SK1199, 2SK1324, 2SK1338
2SK1212	MOS-N-FET-e	V-MOS, S-L, 900V, 5A, 60W, <2,5Ω(2,5A)	17p	Fjd	2SK1119, 2SK1501, 2SK1639, 2SK1643
2SK1213	MOS-N-FET-e	V-MOS, 600V, 6A, 125W, <1,25Ω(3A)	18p	Tos	BUZ332A, 2SK684, 2SK1032
2SK1214	MOS-N-FET-e	V-MOS, LogL, 80V, 20A, 45W, <0,135Ω	17c	Mat	2SK1307, 2SK1348..49, 2SK1432
2SK1215	MOS-N-FET-d	=2SK359: SMD	35c(2mm)	Hit	—
2SK1216	N-FET	SMD, Video-Camera, 10V, 50mA, Idss>9,2mA	35f	Mat	—
2SK1217	MOS-N-FET-e	V-MOS, S-L, 900V, 6A, 100W, <2Ω(4A)	17c(p)	Fjd	—
2SK1221	MOS-N-FET-e	V-MOS, S-L, 250V, 10A, 80W, <0,4Ω(5A)	17p	Fjd	2SK925..26, 2SK1393
2SK1222	MOS-N-FET-e	V-MOS, S-L, 450V, 15A, 125W, <0,55Ω(6A)	18p	Fjd	2SK725, 2SK766, 2SK699, 2SK1610, ++
2SK1223	MOS-N-FET-e	V-MOS, LogL, 60V, 50A, 130W, <45mΩ(13A)	77p	Mat	2SK1390
2SK1224	MOS-N-FET-e	V-MOS, S-L, 800V, 4A, 50W, <4,5Ω(2A)	17c(p)	Fjd	2SK1501, 2SK1639, 2SK1643
2SK1225	MOS-N-FET-e*	=2SK556: Iso, 60W	≈18c	Hit	2SK1268..69, 2SK1328, 2SK1523..24
2SK1227	N-FET	Mikrofon-V, 15V, Zin>200MΩ, Ur<40mV	41a	Tos	—
2SK1228	MOS-N-FET-e	SMD, S, 50V, 50mA, <50Ω(10mA)	35a	Mat	BSS138, BSS145, BST82
2SK1229	GaAs-N-FET	SHF, 4V, 60mA, Idss=12..60mA, 12GHz	51(SGSD)	Hit	—
2SK123	N-FET	SMD, 20V, 2mA, Idss=130..375μA	≈35b	Mat	—
2SK1230	MOS-N-FET-e*	=2SK551: Iso, 25W	17c	Hit	2SK525, 2SK1035
2SK1231	MOS-N-FET-e*	=2SK552: Iso, 30W	17c	Hit	2SK1351, 2SK1608, 2SK1826..27
2SK1232	MOS-N-FET-e*	=2SK553: Iso, 30W	17c	Hit	2SK1351, 2SK1608, 2SK1827
2SK1233	GaAs-N-FET	UHF, 4GHz, 6V, 0,1A, Idss=20..90mA	51(SGSD)	Sey	—
2SK1234	GaAs-N-FET	UHF, 4GHz, 5V, 0,1A, Idss=20..60mA	51(SGSD)	Say	—
2SK1235	GaAs-N-FET	UHF, 12GHz, 6V, 0,1A, Idss=20..90mA	51(SGSD)	Sey	—
2SK1238	GaAs-N-FET	UHF, 12GHz, 6V, 0,1A, Idss=20..90mA	51(SGSD)	Sey	—
2SK1237	GaAs-N-FET	UHF, 12GHz, 5V, 0,1A, Idss=20..60mA	51(SGSD)	Ssy	—
2SK1238	GaAs-N-FET	UHF, 12GHz, 5V, 0,07A, Idss=20..60mA	51(SGSD)	Sey	—
2SK1239	GaAs-N-FET	=2SK1238: Fig. →	52(SGSD)	Ssy	—
2SK124	GaAs-N-FET	UHF, X-Band, 8V, 0,1A, 12GHz	52(SGSD)	Nec	—
2SK1240	GaAs-N-FET	UHF, X-Band, 0,06A, Idss=10..60mA	51(SGSD)	Say	—
2SK1241	GaAs-N-FET	UHF, X-Sand, 0,06A, Idss=10..60mA	51(SGSO)	Say	—
2SK1242	GaAs-N-FET	=2SK1240: Fig. →	52(SGSD)	Say	—
2SK1243	GaAs-N-FET	=2SK1241: Fig. →	52(SGSD)	Say	—
2SK1244	MOS-N-FET-e	V-MOS, 500V, 3A, 40W, <2,3Ω, 45/75ns	17p	Shi	2SK1154, 2SK1494
2SK1245	MOS-N-FET-e	=2SK1244: Iso	15c	Shi	BUK445-500, 2SK1572, 2SK1767
2SK1246	MOS-N-FET-e	V-MOS, 500V, 5A, 50W, <1,4Ω, 50/90ns	17p	Shi	BUZ41A, BUZ90, 2SK1156, 2SK1751, ++
2SK1247	MOS-N-FET-e	=2SK1246: Iso	15c	Shi	2SK1232, 2SK1351, 2SK1608, 2SK1627, ++
2SK1246	MOS-N-FET-e	V-MOS, 500V, 10A, 100W, <0,7Ω, 70/143ns	16p	Shi	2SK724, 2SK896, 2SK1466, 2SK1753, ++
2SK1249	MOS-N-FET-e	V-MOS, 500V, 15A, 130W, <0,45Ω, 100/200ns	16p	Shi	BUZ338, 2SK725, 2SK899, 2SK1810, 2SK1745
2SK125	N-FET	FM/VHF, 25V, Idss>30mA, Up<6V	7e	Sor	BFT10C
2SK1250	MOS-N-FET-e	V-MOS, 500V, 20A, 150W, <0,35Ω, 130/260ns	16p	Shi	2SK1169..70, 2SK1497..1500, 2SK1660, ++
2SK1251	MOS-N-FET-e*	V-MOS, 60V, 5A, 10W, <0,24Ω(2,5A)	≈14c	Tos	—
2SK1252	MOS-N-FET-e*	V-MOS, 120V, 3A, 10W, <0,58Ω(1,5A)	≈14c	Tos	—
2SK1253	MOS-N-FET-e*	V-MOS, LogL, 30V, 30A, 35W, <0,03Ω(15A)	17c	Hit	2SK1262
2SK1254(L,S)	MOS-N-FET-e*	V-MOS, LogL, 100V, 3A, 20W, <0,4Ω(2A)	79p	Hit	2SK1113, 2SK1264
2SK1255	MOS-N-FET-e	V-MOS, LogL, 60V, 5A, 30W, <0,3Ω(2A)	17c	Mat	BUK541-60, BUK542-100, 2SK1260
2SK1256	MOS-N-FET-e	V-MOS, LogL, 60V, 10A, 40W, <0,165Ω(3A)	17c	Mel	2SK1033, 2SK1093, 2SK1305, 2SK1344, ++
2SK1257	MOS-N-FET-e	V-MOS, LogL, 60V, 40A, 45W, <0,05Ω(10)	17c	Mat	2SK1653, 2SK1952

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2SK1258	MOS-N-FET-e	V-MOS, LogL, 60V, 50A, 100W, <45mΩ(13)	18p	Mat	2SK1379, 2SK1381
2SK1259	MOS-N-FET-e	V-MOS, LogL, 60V, 100A, 150W, <23mΩ(25A)	77p	Mat	—
2SK1260	MOS-N-FET-e	V-MOS, LogL, 100V, 5A, 30W, <0,6Ω(2A)	17c	Mat	BUK542-100, 2SK1265
2SK1261	MOS-N-FET-e	V-MOS, LogL, 100V, 8A, 40W, <0,3Ω(3A)	17c	Mat	BUK543-100, 2SK1556
2SK1262	MOS-N-FET-e	V-MOS, LogL, 100V, 30A, 45W, <85mΩ(10A)	17c	Mat	—
2SK1263	MOS-N-FET-e	V-MOS, LogL, 100V, 40A, 100W, <75mΩ(13A)	18p	Mat	2SK1304, 2SK1381
2SK1264	MOS-N-FET-e	V-MOS, LogL, 150V, 3A, 30W, <1,3Ω(2A)	17c	Mat	—
2SK1265	MOS-N-FET-e	V-MOS, LogL, 150V, 8A, 40W, <0,6Ω(3A)	17c	Mat	BUK545-200, 2SK1035
2SK1266	MOS-N-FET-e	V-MOS, LogL, 150V, 20A, 45W, <135mΩ(10A)	17c	Mat	—
2SK1267	MOS-N-FET-e	V-MOS, LogL, 150V, 25A, 100W, <0,13Ω(12A)	18p	Mat	—
2SK1268	MOS-N-FET-e*	=2SK559: Iso, 60W	≈18c	Hit	2SK1331, 2SK1524
2SK1269	MOS-N-FET-e*	=2SK560: Iso, 60W	≈18c	Hit	2SK1331, 2SK1524
2SK127	N-FET	NF, ra, 50V, 20mA, Idss=0,5..12mA	7a	Mat	—
2SK1270	MOS-N-FET-e	=2SK975: 2A, 10W	14b	Hit	2SK1283
2SK1271	MOS-N-FET-e	V-MOS, S-L, 1400V, ±5A, 240W, <4Ω(3A)	18p	Nec	—
2SK1272	MOS-N-FET-e*	V-MOS, LogL, 60V, ±1A, <0,65Ω(0,5A)	7b	Nec	2SK1274, 2SK1733
2SK1273	MOS-N-FET-e*	=2SK1272: SMD, ±2A	39b	Nec	2SK1311, 2SK1470, 2SK1717
2SK1274	MOS-N-FET-e*	=2SK1272: ±1,5A, 1W	9c	Nec	2SK975, 2SK1733, 2SK1738
2SK1275	MOS-N-FET-e*	=2SK1199 Iso, 30W	17c	Hit	2SK1143, 2SK1459
2SK1276	MOS-N-FET-e	V-MOS, S-L, 250V, 20A, 100W, <0,2Ω(10A)	18p	Fjd	2SK901, 2SK944, 2SK1641, 2SK1673..74
2SK1277	MOS-N-FET-e	V-MOS, S-L, 250V, 30A, 150W, <0,12Ω(15A)	18p	Fjd	2SK902, 2SK1492, 2SK1671, 2SK1675..76
2SK1278	MOS-N-FET-e	V-MOS, S-L, 500V, 10A, 100W, <1,1Ω(5A)	18p	Fjd	BUZ339, 2SK724, 2SK896, 2SK1488, 2SK1753
2SK1279	MOS-N-FET-e	V-MOS, S-L, 500V, 15A, 125W, <0,58Ω(8A)	18p	Fjd	BUZ338, 2SK725, 2SK899, 2SK1610, 2SK1678
2SK127A	N-FET	=2SK127: 60V	7a		—
2SK128	N-FET	NF, ra, 30V, 20mA, Idss>0,5mA, Up<1,5V	7a	Mat	2SK68, 2SK106, 2SK164
2SK1280	MOS-N-FET-e	V-MOS, S-L, 500V, 18A, 150W, <0,5Ω(9A)	18p	Fjd	2SK1409, 2SK1411, 2SK1660
2SK1281	MOS-N-FET-e	V-MOS, S-L, 700V, 4A, 120W, <3,2Ω(2A)	18p	Nec	2SK895, 2SK727, 2SK793, 2SK1649..50, ++
2SK1282(Z)	MOS-N-FET-e*	V-MOS, LogL, 60V, ±3A, 20W, <0,18Ω(2A)	30p	Nec	2SK974
2SK1283	MOS-N-FET-e*	=2SK1282:	14j	Nec	2SK1295
2SK1284(Z)	MOS-N-FET-e*	V-MOS, LogL, 100V, ±3A, 20W, <0,32Ω(2A)	30p	Nec	2SK1113, 2SK1254, 2SK1299
2SK1285	MOS-N-FET-e*	=2SK1284:	14j	Nec	—
2SK1286	MOS-N-FET-e*	=2SK1287: Iso, ±15A, 30W	17c	Nec	2SK943, 2SK1214, 2SK1345..46
2SK1287	MOS-N-FET-e*	V-MOS, LogL, 60V, ±20A, 60W, <0,07Ω(10A)	17p	Nec	2SK972, 2SK942, 2SK1115
2SK1288	MOS-N-FET-e*	=2SK1289: Iso, ±15A, 30W	17c	Nec	2SK1034, 2SK1306, 2SK1292, 2SK1558, ++
2SK1289	MOS-N-FET-e*	V-MOS, LogL, 100V, ±20A, 60W, <0,15Ω(10A)	17p	Nec	2SK1116, 2SK1302, 2SK1347
2SK1290	MOS-N-FET-e*	=2SK1291: Iso, ±25A, 35W	17c	Nec	2SK943, 2SK1214, 2SK1345..48
2SK1291	MOS-N-FET-e*	V-MOS, LogL, 60V, ±30A, 75W, <45mΩ(15A)	17p	Nec	2SK1296, 2SK2411
2SK1292	MOS-N-FET-e*	=2SK1293: Iso, ±20A, 35W	17c	Nec	2SK1282, 2SK1307, 2SK1348..49
2SK1293	MOS-N-FET-e*	V-MOS, LogL, 100V, ±30A, 75W, <80mΩ(15A)	17p	Nec	—
2SK1294	MOS-N-FET-e*	V-MOS, LogL, 60V, ±40A, 35W, <27mΩ(20A)	17c	Nec	2SK1257, 2SK1653
2SK1295	MOS-N-FET-e*	V-MOS, LogL, 100V, ±30A, 75W, <50mΩ(15A)	17p	Nec	—
2SK1296	MOS-N-FET-e*	V-MOS, LogL, 60V, 30A, 75W, <28mΩ(15A)	17p	Hit	2SK1291
2SK1297	MOS-N-FET-e*	V-MOS, LogL, 60V, 40A, 100W, <18mΩ(20A)	18p	Hit	2SK1514, 2SK1685
2SK1298	MOS-N-FET-e	=2SK1297: Iso, 50W	18c	Hit	2SK1868
2SK1299(L,S)	MOS-N-FET-e*	V-MOS, LogL, 100V, 3A, 20W, <0,35Ω(2A)	79p	Hit	2SK1113, 2SK1254, 2SK1284
2SK13	N-FET	Uni, ra, 12V, Idss=0,45..5mA, Up<4,5V	5n	Tos	BFS70, 2N3821, 2N4220, 2SK104, ++
2SK130(A)	N-FET	Uni, 30V, 50mA, Idss>5mA, Up<1,5V	7e	Nec	2N5247, 2SK147, 2SK151, 2SK162, 2SK363
2SK1300	MOS-N-FET-e*	V-MOS, LogL, 100V, 10A, 40W, <0,25Ω(5A)	17c	Hit	2SK1559, 2SK1561
2SK1301	MOS-N-FET-e*	V-MOS, LogL, 100V, 15A, 50W, <0,13Ω(8A)	17c	Hit	2SK1559, 2SK1561
2SK1302	MOS-N-FET-e*	V-MOS, LogL, 100V, 20A, 50W, <85mΩ(10A)	17c	Hit	BUK555-100, 2SK1118, 2SK1347
2SK1303	MOS-N-FET-e*	V-MOS, LogL, 100V, 30A, 100W, <0,06Ω(15A)	18c	Hit	2SK1283
2SK1304	MOS-N-FET-e*	V-MOS, LogL, 100V, 40A, 100W, <0,03Ω(20A)	18c	Hit	2SK1263, 2SK1381
2SK1305	MOS-N-FET-e	=2SK1300: Iso, 25W	15c	Hit	BUK545-100, 2SK1035
2SK1306	MOS-N-FET-e	=2SK1301: Iso, 30W	15c	Hit	2SK1034, 2SK1556
2SK1307	MOS-N-FET-e	=2SK1302: Iso, 35W	15c	Hit	2SK1266, 2SK1292, 2SK1348..49
2SK1308	MOS-N-FET-e	V-MOS, S-L, 400V, 5A, 40W, <1,4Ω(3A)	30c	Mat	2SK1891
2SK1308A	MOS-N-FET-e	=2SK1308: 450V	30c		2SK1691
2SK131	N-FET	=2SK130: Dual	7e+7e	Nec	—
2SK1310	MOS-N-FET-e	V-MOS, VHF-L, PO=190W(230MHz)	61	Tos	—
2SK1311	MOS-N-FET-e	SMD, V-MOS, LogL, 60V, 2A, <0,45Ω(1A)	39b	Mat	2SK1273, 2SK1470
2SK1313(L,S)	MOS-N-FET-e*	V-MOS, 450V, 5A, 50W, <1,4Ω(2,5A)	79p	Hit	2SK1540..41, 2SK1722
2SK1314(L,S)	MOS-N-FET-e	=2SK1313: 500V, <1,5Ω(2,5A)	79p	Hit	2SK1541, 2SK1722
2SK1315(L,S)	MOS-N-FET-e*	V-MOS, 450V, 8A, 60W, <0,7Ω(4A)	30p	Hit	2SK2187
2SK1316(L,S)	MOS-N-FET-e*	=2SK1540: 500V, <0,8Ω(4A)	30p	Hit	2SK2187
2SK1317	MOS-N-FET-e	V-MOS, 1500V, 2,5A, 100W, <12Ω(2A)	18c	Hit	2SK1835
2SK1318	MOS-N-FET-e*	V-MOS, 120V, 20A, 35W, <0,12Ω(10A)	17c	Hit	2SK1268

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2SK1319	MOS-N-FET-e	V-MOS, S-L, 250V, 8A, 75W, <0,52Ω(4A)	17p	Mit	2SK741, 2SK1320, 2SK1400
2SK1319..1320S	MOS-N-FET-e	=2SK1319: 1322	30p		2SK1621(250V)
2SK132	MOS-N-FET-e	V-MOS, 100V, 7A, 100W, <1,7Ω, 18/14ns	23e	Hit	2SK175..176, (BUZ33)
2SK1320	MOS-N-FET-e	=2SK1319: 300V	17p	Mit	2SK1400
2SK1321	MOS-N-FET-e	V-MOS, S-L, 450V, 5A, 75W, <1,3Ω(3A)	17p	Mit	BUZ41A..42, 2SK893, 2SK1246, 2SK1751
2SK1321..1322S	MOS-N-FET-e	=2SK1321: 1322	30p		2SK2355Z..56Z
2SK1322	MOS-N-FET-e	=2SK1321: <1,6Ω(3A)	17p	Mit	BUZ41A..42, 2SK893, 2SK1246, 2SK1751
2SK1323	MOS-N-FET-e	V-MOS, S-L, 800V, 2A, 75W, <6,5Ω(1A)	17p	Mit	BUZ80, 2SK1199, 2SK1338
2SK1323..1324S	MOS-N-FET-e	=2SK1323: 1324	30p		2SK1647
2SK1324	MOS-N-FET-e	=2SK1323: 900V	17p	Mit	2SK1199, 2SK1338
2SK1325	GaAs-N-FET	UHF, 6V, 0,12A, Idss=40..120mA, 12GHz	51(6GSD)	Tos	—
2SK1326	N-FET	SMD, Video-Frequ., 10V, 20mA, Idss>6mA	35f	Hit	—
2SK1327(L,S)	MOS-N-FET-e*	V-MOS, 600V, 1A, 20W, <9Ω(0,5A)	30p	Hit	2SK1533, 2SK1880
2SK1328	MOS-N-FET-e*	V-MOS, 450V, 12A, 60W, <0,55Ω(8A)	16c	Hit	2SK1206, 2SK1225, 2SK1268..69, 2SK1523+
2SK1329	MOS-N-FET-e*	=2SK1328: 500V, <0,6Ω(6A)	16c	Hit	2SK1206, 2SK1225, 2SK1269, 2SK1523, ++
2SK133	MOS-N-FET-e	=2SK132: 120V	23e	Hit	2SK175..176, (BUZ33)
2SK1330	MOS-N-FET-e	V-MOS, S-L, 800V, 8A, 100W, <1,7Ω(5A)	16c(p)	Mat	2SK1032, 2SK1358, 2SK1502, 2SK1692, ++
2SK1330A	MOS-N-FET-e	=2SK1330: 900V	16c(p)	Mat	2SK1358, 2SK1502, 2SK1692, 2SK1795, ++
2SK1331	MOS-N-FET-e	V-MOS, S-L, 500V, 15A, 100W, <0,5Ω(8A)	16c	Mat	2SK1269, 2SK1524, 2SK1405
2SK1332	N-FET	=2SK304: SMD	35f(2mm)	Say	—
2SK1333	MOS-N-FET-e	V-MOS, 500V, ±15A, 200W, <0,4Ω(15A)	77p	Tos	2SK678, 2SK1544
2SK1334	MOS-N-FET-e*	V-MOS, 200V, 1A, <3,8Ω(0,5A), 13/17ns	39j	Hit	—
2SK1335(L,S)	MOS-N-FET-e*	V-MOS, 200V, 3A, 20W, <0,8Ω(2A)	79p	Hit	—
2SK1336	MOS-N-FET-e*	V-MOS, LogL, 80V, 0,3A, 0,4W, <1,7Ω(0,2A)	5c	Hit	BST70, BST72, 2SK422..423
2SK1337	MOS-N-FET-e*	V-MOS, LogL, 100V, 0,3A, 0,4W, <4,5Ω(0,2A)	5c	Hit	BSS89, BST74, BST76, 2SK423
2SK1338	MOS-N-FET-e*	V-MOS, 900V, 2A, 50W, <7Ω(1A)	17c	Hit	2SK1199, 2SK1324
2SK1339	MOS-N-FET-e*	V-MOS, 900V, 3A, 80W, <7Ω(1,5A)	16c	Hit	2SK538, 2SK696, 2SK726..727, 2SK794, ++
2SK134	MOS-N-FET-e	=2SK132: 140V	23e	Hit	2SK175..176, (BUZ33)
2SK1340	MOS-N-FET-e*	V-MOS, 900V, 5A, 100W, <4Ω(3A)	16c	Hit	BUZ357..358, 2SK727, 2SK794, 2SK1780, +
2SK1341	MOS-N-FET-e*	V-MOS, 900V, 6A, 100W, <3Ω(3A)	16c	Hit	2SK1358, 2SK1462, 2SK1502, 2SK1614, ++
2SK1342	MOS-N-FET-e*	V-MOS, 900V, 8A, 100W, <1,6Ω(4A)	16c	Hit	2SK1358, 2SK1462, 2SK1502, 2SK1614, ++
2SK1344	MOS-N-FET-e	V-MOS, LogL, 60V, 12A, 80W, <0,07Ω(8A)	17c	Tos	2SK1033, 2SK1094, 2SK1256, 2SK1895, ++
2SK1345	MOS-N-FET-e	V-MOS, LogL, 80V, 20A, 40W, <0,055Ω(10A)	17c	Tos	2SK943, 2SK1095, 2SK1214
2SK1346	MOS-N-FET-e	V-MOS, 80V, 25A, 40W, <0,06Ω(15A)	17c	Tos	2SK943, 2SK1095, 2SK1214, 2SK1420
2SK1347	MOS-N-FET-e	V-MOS, LogL, 100V, 20A, 75W, <65mΩ	17p	Tos	BUK555-100, 2SK1302, 2SK1116
2SK1348	MOS-N-FET-e	=2SK1347: Iso, 40W	17c	Tos	2SK1268, 2SK1307, 2SK1292
2SK1349	MOS-N-FET-e	V-MOS, LogL, 100V, 25A, 45W, <58mΩ	17c	Tos	2SK1262, 2SK1292
2SK135	MOS-N-FET-e	=2SK132: 180V	23e	Hit	2SK175..176, (BUZ33)
2SK1350	MOS-N-FET-e	V-MOS, 200V, 15A, 45W, <0,18Ω(10A)	17c	Tos	—
2SK1351	MOS-N-FET-e	V-MOS, DC-DC, 500V, 5A, 40W, <1,5Ω	17c	Tos	2SK1232, 2SK1608, 2SK1627, 2SK1993, ++
2SK1352	MOS-N-FET-e	V-MOS, DC-DC, 500V, 7A, 45W, <0,85Ω	17c	Tos	2SK1567, 2SK1805
2SK1356	MOS-N-FET-e	V-MOS, S-Reg, 900V, 3A, 40W, <4,3Ω(1,5A)	17c	Tos	2SK1480
2SK1357	MOS-N-FET-e	V-MOS, 900V, 5A, 125W, <2,8Ω(2A)	18p	Tos	2SK727, 2SK794, 2SK1341, 2SK1649..50, ++
2SK1358	MOS-N-FET-e	V-MOS, 900V, 9A, 150W, <1,4Ω(4A)	18p	Tos	2SK1342, 2SK1502, 2SK1614, 2SK1796, ++
2SK1359	MOS-N-FET-e	V-MOS, 1000V, 5A, 125W, <3,6(2A)	18p	Tos	2SK1205
2SK136	N-FET	Uni, ra, 20mA, 30V, Idss>0,5mA, Up<2V	7a	Mat	2N4339, 2N5358, 2SK83
2SK1360	MOS-N-FET-e	V-MOS, SMPS, 900V, 3A, 80W, <4,3Ω	16c	Tos	2SK1463, 2SK1683, 2SK1770
2SK1362	MOS-N-FET-e	V-MOS, SMPS, 900V, 5A, 85W, <2,5Ω(3A)	16c	Tos	2SK1463..65, 2SK1684..85, 2SK1859, ++
2SK1363	MOS-N-FET-e	V-MOS, SMPS, 900V, 8A, 90W, <1,4Ω(4A)	16c	Tos	2SK1465, 2SK1685, 2SK1775
2SK1365	MOS-N-FET-e	V-MOS, SMPS, 1000V, 7A, 90W, <1,8Ω(4A)	16c	Tos	(2SK1120, 2SK1934)
2SK137(A)	N-FET	NF/S, ra, 15V, 50mA, Idss>0,5mA	2l(G=case)	Mat	—
2SK1371	MOS-N-FET-e	V-MOS, S-L, 450V, 20A, 125W, <0,25Ω	23e	Hit	2SK1497, 2SK1499, 2SK1517, 2SK1680, ++
2SK1372	MOS-N-FET-e	=2SK1371: 500V	23	Hit	—
2SK1373	MOS-N-FET-e	V-MOS, S-L, 550V, 12A, 100W, <0,67Ω	18p	Hit	BUZ334, 2SK1723
2SK1374	MOS-N-FET-e	=2SK1228:	35a(2mm)	Mat	—
2SK1375	N-FET	=2SK596: SMD	35f(2mm)	Say	—
2SK1377	MOS-N-FET-e	V-MOS, DC-DC, 400V, 5,5A, 40W, <1,2Ω	17c	Tos	2SK1231, 2SK1351, 2SK1606, 2SK1627, ++
2SK1378	MOS-N-FET-e	V-MOS, DC-DC, 400V, 10A, 125W, <0,55Ω	17p	Tos	BUZ61
2SK1379	MOS-N-FET-e	V-MOS, LogL, 80V, 50A, 150W, <0,017Ω	18p	Tos	BUK539-60, 2SK1258
2SK138	GaAs-FET	UHF, X-Band, 5V, 100mA, 8GHz	52(SGSD)	Nec	—
2SK1380	MOS-N-FET-e	V-MOS, LogL, 80V, 60A, 200W, <0,011Ω	77p	Tos	2SK1259
2SK1381	MOS-N-FET-e	V-MOS, LogL, 100V, 50A, 150W, <0,032Ω	18p	Tos	—
2SK1382	MOS-N-FET-e	V-MOS, LogL, 100V, 80A, 200W, <0,02Ω	77p	Tos	—
2SK1383	SIT-N-FET-e	Static Inductive Trans., 200V, 3A	2a		—
2SK1384	MOS-N-FET-e	V-MOS, S-L, 800V, 5A, 80W, <2Ω(2,5A)	16c(p)	Fjd	—
2SK1385	MOS-N-FET-e	V-MOS, S-L, 800V, 9A, 100W, <1,5Ω(4A)	18c(p)	Fjd	2SK1686

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2SK1386	MOS-N-FET-e	V-MOS, S-L, 450V, 7A, 100W, <1,3Ω(3A)	18p	Fjd	BUZ330..331
2SK1387	MOS-N-FET-e	V-MOS, 60V, 35A, 40W, <0,035Ω(17,5A)	≈15c	Fjd	2SK1653
2SK1388	MOS-N-FET-e	V-MOS, 30V, 35A, 60W, <0,022Ω(17,5A)	17p	Fjd	BUK555-50
2SK1389	MOS-N-FET-e	V-MOS, 60V, 50A, 125W, <0,025Ω(25A)	18p	Fjd	2SK1258, 2SK1379
2SK1390	MOS-N-FET-e	=2SK1389: 80W	18c(p)	Fjd	2SK1298, 2SK1666
2SK1391	MOS-N-FET-e	V-MOS, 250V, 6A, 40W, <0,84Ω, 65/60ns	17p	Shi	2SK477, 2SK741, 2SK924
2SK1392	MOS-N-FET-e	=2SK1381: Iso, 25W	15c	Shi	2SK1478, 2SK1588, 2SK1668
2SK1393	MOS-N-FET-e	V-MOS, 250V, 10A, 50W, <0,5Ω, 75/100ns	17p	Shi	2SK925..926, 2SK1221, 2SK1393
2SK1394	MOS-N-FET-e	=2SK1393: Iso, 30W	15c	Shi	2SK526, 2SK1036, 2SK1762
2SK1395	MOS-N-FET-e	V-MOS, 250V, 20A, 100W, <0,25Ω	16p	Shi	2SK623, 2SK901, 2SK944, 2SK1641, 2SK167
2SK1396	MOS-N-FET-e	V-MOS, 250V, 30A, 120W, <0,18Ω	16p	Shi	2SK902, 2SK1669, 2SK1671, 2SK1675
2SK1397	MOS-N-FET-e	V-MOS, 250V, 40A, 130W, <0,13Ω	18p	Shi	—
2SK1396	MOS-N-FET-e	V-MOS, S, 50V, ±0,1A, 0,25W, <20Ω(10mA)	40c	Nec	BS170, BSS98
2SK1399	MOS-N-FET-e	=2SK1396: SMD	35a	Nec	BSS123, BSS138, BSS145
2SK140	GaAs-FET	UHF, X-Band, 5V, 100mA, 12GHz	52(SGSD)	Nec	—
2SK1400	MOS-N-FET-e	V-MOS, 300V, 7A, 50W, <0,7Ω(4A)	17p	Hit	2SK554..555, 2SK1320
2SK1400A	MOS-N-FET-e	=2SK1400: 350V, <0,8Ω(4A)	17c		2SK554..555, 2SK1495..96
2SK1401	MOS-N-FET-e	V-MOS, 300V, 15A, 100W, <0,35Ω(8A)	18p	Hit	BUZ323
2SK1401A	MOS-N-FET-e	=2SK1401: 350V, <0,4Ω(8A)	16c		BUZ323
2SK1402	MOS-N-FET-e	V-MOS, 600V, 4A, 50W, <2,4Ω(2A)	17p	Hit	BUZ90, 2SK1117
2SK1402A	MOS-N-FET-e	=2SK1402: 650V, <2,6Ω(2A)	17c		—
2SK1403	MOS-N-FET-e	V-MOS, 600V, 8A, 100W, <1,3Ω(4A)	18p	Hit	2SK684, 2SK1032
2SK1403A	MOS-N-FET-e	=2SK1403: 650V, <1,4Ω(4A)	16c		2SK664, 2SK1032
2SK1404	MOS-N-FET-e	V-MOS, 600V, 5A, 35W, <1,5Ω(2,5A)	15c	Hit	2SK1118, 2SK1637
2SK1405	MOS-N-FET-e	FREDFET, 600V, 15A, 60W, <0,5Ω(8A)	16c	Hit	—
2SK1406	MOS-N-FET-e	V-MOS, S-L, 500V, 20A, 100W, <0,4Ω(10A)	16c	Mat	2SK1525
2SK1407	GaAs-N-FET	UHF-Converter, 4V, 60mA, 12GHz	51(SGSD)	Rhr	—
2SK1408	MOS-N-FET-e	V-MOS, S-L, 450V, 18A, 200W, <0,31Ω(8A)	≈16c	Mit	—
2SK1409	MOS-N-FET-e	V-MOS, S-L, 450V, 20A, 250W, <0,25Ω(10A)	≈18c	Mit	—
2SK141(A)	N-FET	Uni, 50V, 20mA, Idss>0,5mA, Up<4,5V	2b	Nec	BFS70, 2N3821, 2N4220, 2SK104, ++
2SK1410	MOS-N-FET-e	=2SK1406: 500V	≈18c	Mit	—
2SK1411	MOS-N-FET-e	=2SK1409: 500V	≈16c	Mit	—
2SK1412(L,S)	MOS-N-FET-e	V-MOS, 1500V, 0,1A, 20W, <200Ω(50mA)	17c	Say	—
2SK1413	MOS-N-FET-e	V-MOS, 1500V, 2A, 80W, <11Ω(1A)	18c	Say	—
2SK1414	MOS-N-FET-e	V-MOS, 1500V, 8A, 200W, <3,5Ω(3A)	77p	Say	—
2SK1415	GaAs-N-FET-d	SHF, 3,5V, 60mA, Idss=12..60mA, 12GHz		Hit	—
2SK1416	MOS-N-FET-e	V-MOS, S-L, 60V, 15A, 40W, <0,08Ω(10A)	17p	Say	BUK552-60, 2SK971..72, 2SK1115
2SK1417	MOS-N-FET-e	V-MOS, S-L, 60V, 25A, 60W, <45mΩ(15A)	17p	Say	BUK555-60, 2SK972, 2SK1115, 2SK1296
2SK1418	MOS-N-FET-e	V-MOS, S-L, 60V, 40A, 70W, <26mΩ(25A)	17p	Sav	BUK556-60, 2SK1542
2SK1419	MOS-N-FET-e	V-MOS, S-L, 60V, 15A, 25W, <0,08Ω(10A)	17c	Say	2SK943, 2SK1345..46
2SK1420	MOS-N-FET-e	V-MOS, S-L, 60V, 25A, 30W, <45mΩ(15A)	17c	Say	2SK943, 2SK1345..46
2SK1421	MOS-N-FET-e	V-MOS, S-L, 60V, 40A, 40W, <26mΩ(25A)	17c	Say	2SK1257, 2SK1853
2SK1422	MOS-N-FET-e	V-MOS, 60V, 50A, 100W, <26mΩ(25A)	18p	Say	BUK539-60, 2SK1258, 2SK1379
2SK1423	MOS-N-FET-e	V-MOS, S-L, 60V, 80A, 150W, <16mΩ(50A)	18p	Say	—
2SK1424	MOS-N-FET-e	V-MOS, S-L, 60V, 40A, 60W, <26mΩ(25A)	18c	Say	2SK1298, 2SK1668
2SK1425	MOS-N-FET-e	V-MOS, S-L, 60V, 60A, 80W, <16mΩ(50A)	16c	Say	—
2SK1426	MOS-N-FET-e	V-MOS, S-L, 60V, 100A, 200W, <12mΩ(60A)	77p	Say	2SK1259
2SK1427	MOS-N-FET-e	V-MOS, S-L, 100V, 10A, 40W, <0,16Ω(8A)	17p	Say	2SK1300
2SK1428	MOS-N-FET-e	V-MOS, S-L, 100V, 20A, 60W, <0,1Ω(12A)	17p	Say	BUK555-100, 2SK1302, 2SK1118, 2SK1347
2SK1429	MOS-N-FET-e	V-MOS, S-L, 100V, 30A, 70W, <55mΩ(20A)	17p	Say	BUK456-100, 2SK1303
2SK1430	MOS-N-FET-e	V-MOS, S-L, 100V, 10A, 25W, <0,16Ω(8A)	17c	Say	BUK545-100, 2SK1035, 2SK1305
2SK1431	MOS-N-FET-e	V-MOS, S-L, 100V, 15A, 30W, <0,1Ω(12A)	17c	Say	BUK445-100, 2SK1306, 2SK1556
2SK1432	MOS-N-FET-e	V-MOS, S-L, 100V, 25A, 40W, <55mΩ(20A)	17c		2SK1307, 2SK1348..49
2SK1433	MOS-N-FET-e	V-MOS, S-L, 100V, 30A, 100W, <55mΩ(20A)	18p	Say	2SK1303
2SK1434	MOS-N-FET-e	V-MOS, S-L, 100V, 60A, 150W, <35mΩ(40A)	18p	Say	2SK1381
2SK1435	MOS-N-FET-e	V-MOS, S-L, 100V, 30A, 80W, <55mΩ(20A)	18c	Say	2SK1149
2SK1438	MOS-N-FET-e	V-MOS, S-L, 100V, 50A, 80W, <35mΩ(40A)	18c	Say	2SK1149
2SK1437	MOS-N-FET-e	V-MOS, S-L, 100V, 70A, 200W, <26mΩ(45A)	77p	Say	2SK1382
2SK1438	MOS-N-FET-e	V-MOS, S-L, 450V, 0,3A, 20W, <12Ω(0,2A)	17p	Say	(2SK1052)
2SK1438	MOS-N-FET-e	V-MOS, S-L, 450V, 3A, 50W, <2,6Ω(1,5A)	17p	Say	2SK1154, 2SK1244
2SK1440	MOS-N-FET-e	V-MOS, S-L, 450V, 5A, 60W, <1,4Ω(3A)	17p	Say	2SK1246, (BUZ41A..42, 2SK552..53, 2SK893)
2SK1441	MOS-N-FET-e	V-MOS, S-L, 450V, 8A, 70W, <0,8Ω(4A)	17p	Say	(2SK554..55, 2SK636, 2SK894)
2SK1442	MOS-N-FET-e	V-MOS, S-L, 450V, 12A, 70W, <0,6Ω(6A)	17p	Say	2SK1503
2SK1443(L,S)	MOS-N-FET-e	V-MOS, S-L, 450V, 1A, 20W, <4,5Ω(0,5A)	17c	Sav	2SK1833, (BUK444-450, 2SK529, 2SK1833)
2SK1444(L,S)	MOS-N-FET-e	V-MOS, S-L, 450V, 3A, 25W, <2,6Ω(1,5A)	17c	Sav	BUK445-450, 2SK1572, 2SK1767
2SK1445(L,S)	MOS-N-FET-e	V-MOS, S-L, 450V, 5A, 30W, <1,4Ω(3A)	17c	Sav	2SK1351, 2SK1608, 2SK1626, 2SK1990..93

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2SK1446(L,S)	MOS-N-FET-e	V-MOS, S-L, 450V, 7A, 35W, <0,8Ω(4A)	17c	Say	2SK1352, 2SK1566..67, 2SK1609
2SK1447(L,S)	MOS-N-FET-e	V-MOS, S-L, 450V, 9A, 40W, <0,6Ω(6A)	17c	Say	—
2SK1448	MOS-N-FET-e	V-MOS, S-L, 450V, 8A, 100W, <0,8Ω(4A)	18p	Sav	2SK1574, (BUZ330..331)
2SK1449	MOS-N-FET-e	V-MOS, S-L, 450V, 12A, 120W, <0,6Ω(6A)	18p	Say	2SK1488, 2SK1810, 2SK1745, 2SK1785, ++
2SK1450	MOS-N-FET-e	V-MOS, S-L, 450V, 20A, 150W, <0,3Ω(10A)	18p	Sav	2SK1169..70, 2SK1497..1500, 2SK1680, ++
2SK1451	MOS-N-FET-e	V-MOS, S-L, 450V, 8A, 50W, <0,8Ω(4A)	18c	Say	2SK1206, 2SK1225, 2SK1328, 2SK1523
2SK1452	MOS-N-FET-e	V-MOS, S-L, 450V, 10A, 60W, <0,6Ω(6A)	18c	Say	2SK1206, 2SK1225, 2SK1328, 2SK1523
2SK1453	MOS-N-FET-e	V-MOS, S-L, 450V, 16A, 70W, <0,3Ω(10A)	18c	Say	2SK1288..69, 2SK1331, 2SK1524..25
2SK1454	MOS-N-FET-e	V-MOS, S-L, 450V, 30A, 250W, <0,18Ω(15A)	77p	Say	2SK1628..29
2SK1455	MOS-N-FET-e	V-MOS, S-L, 900V, 0,2A, 30W, <70Ω(0,1A)	17p	Say	—
2SK1458	MOS-N-FET-e	V-MOS, S-L, 900V, 3A, 60W, <6Ω(1,5A)	17p	Say	BUK 456-1000, 2SK1601, 2SK1838, 2SK1793
2SK1457	MOS-N-FET-e	V-MOS, S-L, 900V, 5A, 70W, <3,6Ω(2A)	17p	Say	2SK1501, 2SK1639, 2SK1643
2SK1458(LS)	MOS-N-FET-e	V-MOS, S-L, 900V, 0,2A, 20W, <70Ω(0,1A)	17c	Say	—
2SK1459(LS)	MOS-N-FET-e	V-MOS, S-L, 900V, 2,5A, 30W, <8Ω(1,5A)	17c	Say	2SK1143, 2SK1275
2SK146	N-FET	=2SK147: Dual	7e+7a	Tos	—
2SK1460(LS)	MOS-N-FET-e	V-MOS, S-L, 900V, 3,5A, 40W, <3,6Ω(2A)	17c	Sey	2SK1358
2SK1461	MOS-N-FET-e	V-MOS, S-L, 900V, 5A, 120W, <3,6Ω(2A)	18p	Sey	2SK727, 2SK794, 2SK1649..50, 2SK1760, ++
2SK1462	MOS-N-FET-e	V-MOS, S-L, 900V, 8A, 150W, <1,6Ω(4A)	18p	Say	2SK1358, 2SK1502, 2SK1614, 2SK1795, ++
2SK1463	MOS-N-FET-a	V-MOS, S-L, 900V, 4,5A, 60W, <3,8Ω(2A)	18c	Say	2SK1884, 2SK1859
2SK1464	MOS-N-FET-e	V-MOS, S-L, 900V, 6A, 80W, <1,6Ω(4A)	18c	Say	2SK1685
2SK1465	MOS-N-FET-e	V-MOS, S-L, 900V, 6A, 200W, <1,6Ω(4A)	77p	Say	2SK1489
2SK1466	MOS-N-FET-e	V-MOS, S-L, 900V, 18A, 250W, <0,8Ω(6A)	77p	Sey	—
2SK1467	MOS-N-FET-e*	SMD, LogL, V-MOS, S, 30V, 2A, <0,3Ω(1A)	39b	Sey	2SK1311, 2SK1470, 2SK1717
2SK1466	MOS-N-FET-e*	V-MOS, LogL, 30V, 4A, 20W, <0,12Ω(2A)	30c	Say	2SK1112, 2SK1471, 2SK1718
2SK1469	MOS-N-FET-e*	V-MOS, LogL, 30V, 8A, 30W, <0,055Ω(4A)	30c	Say	2SK1472, 2SK1748
2SK147	N-FET	Uni, ra, 40V, Idss>5mA, Up<1,2V	7a(9mm)	Tos	2N5247, 2SK130, 2SK151, 2SK182, 2SK363
2SK1470	MOS-N-FET-e*	SMD, V-MOS, LogL, 60V, 2A, <0,45Ω(1A)	39b	Say	2SK1311, 2SK1717, 2SK1763
2SK1471	MOS-N-FET-e*	V-MOS, LogL, 60V, 4A, 20W, <0,2Ω(2A)	30c	Sey	2SK1112, 2SK1474, 2SK1719
2SK1472	MOS-N-FET-e*	V-MOS, LogL, 60V, 8A, 30W, <0,08Ω(4A)	30c	Say	2SK1475, 2SK1748
2SK1473	MOS-N-FET-e*	SMD, V-MOS, LogL, 100V, 2A, <0,95Ω(1A)	39b	Say	2SK2055
2SK1474	MOS-N-FET-e*	V-MOS, LogL, 100V, 4A, 20W, <0,4Ω(2A)	30c	Say	2SK1804
2SK1475	MOS-N-FET-e*	V-MOS, LogL, 100V, 8A, 30W, <0,16Ω(4A)	30c	Say	2SK1557
2SK1478	MOS-N-FET-e	V-MOS, S-L, 450V, 12A, 150W, <0,85Ω(8A)	≈18p	Mit	2SK896, 2SK1488, 2SK1752, 2SK1785, ++
2SK1477	MOS-N-FET-e	=2SK1478: 500V, <0,78Ω(6A)	≈18p	Mit	2SK896, 2SK1488, 2SK1753, 2SK1785, ++
2SK1478	MOS-N-FET-e	V-MOS, S-L, 250V, 8A, 40W, <0,8Ω(2A)	17c	Ma1	2SK526, 2SK1036, 2SK1566..69
2SK1479	N-FET	SMD, Imped-Conv., 25V, 5mA, Idss>0,3mA	35f	Hit	—
2SK148	N-FET	FM/VHF, 25V, Idss<12mA	9e	Ma1	—
2SK1480	MOS-N-FET-d	SMD, FM/VHF, 20V, ±30mA, Idss>1mA, Up<2V	35e	Nec	—
2SK1482	MOS-N-FET-e*	V-MOS, 30V, ±1,5A, 0,75W, <0,4Ω(0,5A)	7b	Nec	2SK1272, 2SK1733
2SK1483	MOS-N-FET-e*	=2SK1462: SMD, ±2A	39b	Nec	2SK1273, 2SK1311, 2SK1470
2SK1484	MOS-N-FET-a*	V-MOS, 100V, ±0,5A, 0,75W, <0,8Ω(0,5A)	7b	Nec	2SK1729
2SK1485	MOS-N-FET-e*	=2SK1484: SMD, ±1A	39b	Nec	2SK1728
2SK1488	MOS-N-FET-e	V-MOS, 300V, 32A, 200W, <0,095Ω(18A)	77p	Tos	—
2A12882SK1467	MOS-N-FET-e	V-MOS, 450V, 10A, 125W, <1Ω(5A)	18p	Tos	2SK896, 2SK1488, 2SK1723, 2SK1752, ++
2SK1488	MOS-N-FET-e	V-MOS, 500V, 10A, 125W, <1Ω(5A)	18p	Tos	2SK896, 2SK1723, 2SK1753, 2SK1785, ++
2SK1489	MOS-N-FET-e	V-MOS, 1000V, 12A, 200W, <1Ω(6A)	77p	Tos	—
2SK149	N-FET	UHF, 20V, Idss>8mA, Up<2,2V	5m	Nec	—
2SK1491	MOS-N-FET-e*	V-MOS, S-L, 250V, ±25A, 120W, <0,15Ω(13A)	18p	Nec	2SK901, 2SK944, 2SK1641, 2SK1673..74
2SK1492	MOS-N-FET-e*	V-MOS, S-L, 250V, ±35A, 140W, <0,1Ω(18A)	18p	Nec	2SK902, 2SK1669, 2SK1671, 2SK1675..76
2SK1493	MOS-N-FET-e*	V-MOS, S-L, 450V, ±3A, 50W, <2,8Ω(2A)	17p	Nec	2SK1154, 2SK1244, 2SK1439
2SK1493..1494Z	MOS-N-FET-e*	=2SK1493: 1494	30c		2SK2356Z
2SK1493..1496Z	MOS-N-FET-e*	=2SK1493: 1496	30c		2SK1540..41
2SK1494	MOS-N-FET-e*	=2SK1493: 500V, <3Ω(2A)	17p	Nec	2SK1154, 2SK1244
2SK1495	MOS-N-FET-e*	V-MOS, S-L, 450V, ±7A, 70W, <0,9Ω(4A)	17p	Nec	IRF840, IRF842, 2SK1574
2SK1496	MOS-N-FET-e*	=2SK1495: 500V, <1Ω(4A)	17p	Nec	IRF840, IRF842, 2SK1574
2SK1497	MOS-N-FET-e*	V-MOS, S-L, 450V, ±20A, 120W, <0,35Ω(10A)	18p	Nec	2SK1189..70, 2SK1409, 2SK1411, 2SK1680
2SK1498	MOS-N-FET-e*	=2SK1497: 500V, <0,4Ω(10A)	18p	Nec	2SK1170, 2SK1411, 2SK1880
2SK1499	MOS-N-FET-e*	V-MOS, S-L, 450V, ±25A, 160W, <0,25Ω(13A)	18p	Nec	2SK1169..70, 2SK1409, 2SK1411, 2SK1880
2SK15	N-FET	Uni, ra, 20V, Idss=0,45..5mA, Up<6V	5n	Tos	BFS70, 2N3821, 2N4220, 2SK104, ++
2SK150	N-FET	Dual, 50V, Idss>1mA, Up<2V	7-SIP	Tos	—
2SK1500	MOS-N-FET-e*	=2SK1499: 500V, <0,27Ω(13A)	18p	Nec	2SK1170, 2SK1411, 2SK1680
2SK1501	MOS-N-FET-e*	V-MOS, S-L, 900V, ±4A, 70W, <4Ω(2A)	17p	Nec	2SK1119, 2SK1457, 2SK1639, 2SK1843
2SK1501Z	MOS-N-FET-e	=2SK1501:	30c		—
2SK1502	MOS-N-FET-e*	V-MOS, S-L, 900V, ±7A, 120W, <2Ω(2A)	18p	Nec	2SK1358, 2SK1814, 2SK1692, 2SK1795
2SK1503	MOS-N-FET-e	V-MOS, S-L, 500V, 10A, 80W, <0,9Ω(5A)	17p	Fjd	2SK2366
2SK1504(L,S)	MOS-N-FET-e	=2SK1503:	30p	Fjd	2SK2366Z

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2SK1505	MOS-N-FET-e	V-MOS, S-L, 30V, 35A, 40W, <0,022Ω	~15c	Fjd	—
2SK1506	MOS-N-FET-e	V-MOS, 120V, 50A, 150W, <0,03Ω(25A)	18p	Fjd	—
2SK1507	MOS-N-FET-e	V-MOS, 600V, 9A, 50W, <1Ω(5A)	17c	Fjd	—
2SK1508	MOS-N-FET-e	V-MOS, 80V, 35A, 60W, <35mΩ(17,5A)	17p	Fjd	BUK555-60, 2SK1291, 2SK1296
2SK1509	MOS-N-FET-e	V-MOS, 100V, 20A, 60W, <80mΩ(10A)	17p	Fjd	BUZ21, IRF540, IRF542, 2SK1116, ++
2SK151	N-FET	NF/S, ra, 40V, Idss>6mA, Up<1,1V	7a(9mm)	Hit	2N5247
2SK1510(L,S)	MOS-N-FET-e	V-MOS, S-L, 900V, 3,5A, 60W, <5,5Ω(2A)	30p	Fjd	2SK1528
2SK1511	MOS-N-FET-e	V-MOS, 1000V, 5A, 100W, <3Ω		Fjd	—
2SK1512	MOS-N-FET-e	V-MOS, 900V, 10A, 150W, <1,2Ω		Fjd	—
2SK1513	MOS-N-FET-e	V-MOS, 500V, 8A, 150W, <0,75Ω(8A)	77p	Tos	2SK1029
2SK1514	MOS-N-FET-e*	V-MOS, LogL, 80V, 40A, 125W, <0,03Ω(20A)	18p	Hit	2SK1297, 2SK1665
2SK1515	MOS-N-FET-e*	FREDFET, 450V, 10A, 100W, <0,6Ω(5A)	16c	Hit	BUK637-450, 2SK663
2SK1516	MOS-N-FET-e*	=2SK1515: 500V, <0,9Ω(5A)	16c	Hit	BUK637-500, 2SK683
2SK1517	MOS-N-FET-e*	FREDFET, 450V, 20A, 120W, <0,25Ω(10A)	16c	Hit	—
2SK1518	MOS-N-FET-e*	=2SK1517: 500V, <0,27Ω(10A)	16c	Hit	—
2SK1519	MOS-N-FET-e*	FREDFET, 450V, 30A, 200W, <0,15Ω(15A)	47c	Hit	—
2SK152	N-FET	FMA/HF, 15V, Idss>9,5mA, Up<2V	7d	Son	BF410D
2SK1520	MOS-N-FET-e*	=2SK1519: 500V, <0,16Ω(15A)	47c	Hit	—
2SK1521	MOS-N-FET-e*	FREDFET, 450V, 50A, 250W, <0,1Ω(25A)	47c	Hit	—
2SK1522	MOS-N-FET-e*	=2SK1521: 500V, <0,11Ω(25A)	47c	Hit	—
2SK1523	MOS-N-FET-e	=2SK1248: Iso	16c	Shi	2SK1206
2SK1524	MOS-N-FET-e	=2SK1249: Iso	18c	Shi	2SK1269, 2SK1331, 2SK1405
2SK1525	MOS-N-FET-e	=2SK1250: Iso	18c	Shi	2SK1406
2SK1526	MOS-N-FET-e*	V-MOS, 450V, 40A, 250W, <0,15Ω(20A)	47c	Hit	2SK1521..22
2SK1527	MOS-N-FET-e*	=2SK1526: 500V, <0,16Ω(20A)	47c	Hit	2SK1522
2SK1526(L,S)	MOS-N-FET-e*	V-MOS, 900V, 4A, 60W, <4Ω(2A)	79p	Hit	2SK2006
2SK1529	MOS-N-FET-e	V-MOS, NF-E, 180V, 10A, 120W	18p	Tos	—
2SK1530	MOS-N-FET-e	V-MOS, NF-E, 200V, 12A, 150W	77p	Tos	—
2SK1531	MOS-N-FET-e	V-MOS, 500V, 15A, 150W, 0,45Ω(7A)	18p	Tos	2SK725, 2SK788, 2SK899, 2SK1745, 2SK1678
2SK1532	N-FET	=2SK1031:	35l(2mm)	Hit	—
2SK1533	MOS-N-FET-e	V-MOS, 900, 1A, 10W, <15Ω, 40/85ns	30p	Shi	—
2SK1534	MOS-N-FET-e	V-MOS, 900, 3A, 50W, <5Ω, 45/110ns	17p	Shi	2SK791..792, 2SK1456, 2SK1801, 2SK1638++
2SK1535	MOS-N-FET-e	=2SK1534: Iso, 30W	15c	Shi	2SK1356, 2SK1460
2SK1538	MOS-N-FET-e	V-MOS, 900V, 3A, 70W, <5Ω, 45/110ns	16p	Shi	2SK726, 2SK1339
2SK1537	MOS-N-FET-e	V-MOS, 900V, 5A, 100W, <3Ω, 65/145ns	18p	Shi	2SK727, 2SK794, 2SK1649..50, 2SK1794, ++
2SK1538	MOS-N-FET-e	V-MOS, 900V, 7A, 130W, <2Ω, 80/200ns	18p	Shi	2SK1342, 2SK1356, 2SK1462, 2SK1795, ++
2SK1539	MOS-N-FET-e	V-MOS, 900V, 10A, 150W, <1,4Ω, 115/290ns	16p	Shi	2SK1796
2SK154	N-FET	FM/VHF, 20V, Idss<18mA	71	Mat	—
2SK1540(L,S)	MOS-N-FET-e	V-MOS, 450V, 7A, 60W, <0,6Ω(4A)	79p	Hit	2SK1315..16, 2SK2187
2SK1541(L,S)	MOS-N-FET-e	=2SK1540 500V, <0,9Ω(4A)	79p	Hit	2SK1316, 2SK2187
2SK1542	MOS-N-FET-e	V-MOS, LogL, 80V, 45A, 125W, <0,02Ω(20A)	17p	Tos	BUK556-60
2SK1544	MOS-N-FET-e	V-MOS, 500V, 25A, 200W, <0,2Ω(13A)	77p	Tos	2SK1629
2SK1545	MOS-N-FET-e	V-MOS, 800V, 3A, 40W, <6Ω		Fjd	—
2SK1546	MOS-N-FET-e	V-MOS, 900V, 2,5A, 40W, <7,3Ω		Fjd	—
2SK1547	MOS-N-FET-e	V-MOS, 800V, 4A, 40W, <4,5Ω(2A)	17c	Fjd	2SK1404, 2SK1637, 2SK2118
2SK1548	MOS-N-FET-e	V-MOS, 900V, 3,5A, 40W, <5,5Ω(2A)	17c	Fjd	2SK1358, 2SK1460
2SK1549	MOS-N-FET-e	V-MOS, 250V, 20A, 80W, <0,15Ω(10A)	16c	Fjd	2SK822
2SK155	N-FET	Uni, ra, 20V, Idss>0,5mA, Up<1,5V	7a	Mat	2SK66, 2SK106, 2SK164
2SK1550	MOS-N-FET-e	V-MOS, 600V, 4A, 40W, <1,8Ω		Fjd	—
2SK1552(L,S)	MOS-N-FET-e	V-MOS, 800V, 4A, 60W, <4,5Ω(2A)	80p	Fjd	2SK1528
2SK1553	MOS-N-FET-e	V-MOS, 650V, 5A, 40W, <2,5Ω(2,5A)	17c	Fjd	2SK1404, 2SK1637, 2SK2118
2SK1554	MOS-N-FET-e	V-MOS, 650V, 3A, 30W, <4,5Ω		Fjd	—
2SK1555	MOS-N-FET-e	V-MOS, LogL, 50V, 16A, 75W, <0,05Ω(8A)	17p	Mit	BUK552-50, 2SK971
2SK1555S	MOS-N-FET-e	=2SK1555:	30p		2SK1648, 2SK1898, 2SK2322
2SK1556	MOS-N-FET-e	V-MOS, S-L, 100V, 8A, 30W, <0,2Ω(4A)	17c	Mit	BUK543-100, 2SK1281
2SK1557	MOS-N-FET-e	=2SK1556: 45W	30p	Mit	2SK1475
2SK1556	MOS-N-FET-e	V-MOS, LogL, 100V, 15A, 40W, <0,09Ω(8A)	17c	Mit	2SK1034, 2SK1288, 2SK1306
2SK1559	MOS-N-FET-e	=2SK1556: 75W	17p	Mit	2SK1301, 2SK1561
2SK1559S	MOS-N-FET-e	=2SK1558:	30p		—
2SK156	N-FET	NF-V, 20V, Idss>0,06mA	41e	Say	—
2SK1560	MOS-N-FET-e	V-MOS, LogL, 150V, 7A, 45W, <0,3Ω(4A)	30p	Mit	—
2SK1561	MOS-N-FET-e	V-MOS, LogL, 150V, 18A, 75W, <0,12Ω(8A)	17p	Mit	BUK555-200
2SK1561S	MOS-N-FET-e	=2SK1561:	30p		—
2SK1562	MOS-N-FET-e	V-MOS, S-L, 450V, 12A, 150W, <0,65Ω(8A)	17p	Mit	—
2SK1562..1563S	MOS-N-FET-e	=2SK1562: 1563	30p		—
2SK1563	MOS-N-FET-e	=2SK1562: 500V, <0,78Ω(8A)	17p	Mit	—

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2SK1564	MOS-N-FET-e	V-MOS, S-L, 800V, 3A, 150W, <3,6Ω(1,5A)	17p	Mit	—
2SK1564..1565S	MOS-N-FET-e	=2SK1564: 1565	30p		—
2SK1565	MOS-N-FET-e	=2SK1564: 900V, <4Ω(1,5A)	17p	Mit	—
2SK1566	MOS-N-FET-e	=2SK1157: Iso, 35W	15c	Hit	2SK1352, 2SK1609, 2SK1805
2SK1567	MOS-N-FET-e	=2SK1156: Iso, 35W	15c	Hit	2SK1352, 2SK1609, 2SK1805
2SK1568	MOS-N-FET-e	V-MOS, S-L, 250V, 8A, 40W, <0,6Ω(4A)	17c	Mit	2SK1478, 2SK1668
2SK1569	MOS-N-FET-e	=2SK1468: 300V, <0,65Ω(4A)	17c	Mit	—
2SK157	N-FET	SMD, 50V, Idss>0,5mA, Up<1,5V	35f	Hit	2SK94
2SK1570	MOS-N-FET-e	V-MOS, S-L, 450V, 12A, 150W, <0,78Ω(8A)	≈18c	Mit	2SK683, 2SK1488, 2SK1516, 2SK1785, ++
2SK1571	MOS-N-FET-e	=2SK1570: 500V, <0,9Ω(8A)	≈18c	Mit	2SK683, 2SK1488, 2SK1516, 2SK1785, ++
2SK1572	MOS-N-FET-e*	V-MOS, 800V, 3A, 25W, <5Ω(1A), 33/95ns	15c	Hit	2SK1767, 2SK2144
2SK1573	MOS-N-FET-e*	V-MOS, 600V, 15A, 125W, <0,5Ω(8A)	18c	Hit	2SK1723
2SK1574	MOS-N-FET-e	V-MOS, 500V, 8A, 125W, <0,85Ω(4A)	17p	Tos	IRF 840, 2SK694, 2SK1496
2SK1575	MOS-N-FET-e*	V-MOS, Dual, 180V, 18A, PQ>160W(190MHz)	≈	Hit	—
2SK1576	N-FET	SMD, NF/HF, 30V, Idss=2,5..14mA, Up<1,5V	35f	Son	—
2SK1577	N-FET	SMD, VHF/UHF, C951235V, Idss>30mA, Up<6V	35f	Son	—
2SK1576	N-FET	Mikroton-V, 20V, 10mA, Idss>0,1mA, Up<1,5V	40e	Say	—
2SK1579	MOS-N-FET-e*	SMD, V-MOS, Rgate, 12V, ±2A, 500/1500ns	39j	Hit	—
2SK158	N-FET	SMD, 55V, Idss<6,5mA	35b	Mat	—
2SK1580	MOS-N-FET-e*	SMD, V-MOS, 16V, ±0,1A, <10Ω(1mA)	35a(2mm)	Nec	—
2SK1581	MOS-N-FET-e*	SMD, V-MOS, 16V, ±0,2A, <3Ω(1mA)	35a	Nec	BSS 123
2SK1582	MOS-N-FET-e*	SMD, V-MOS, 30V, ±0,2A, <3Ω(10mA)	35a	Nec	BSS 123
2SK1563	MOS-N-FET-e*	SMD, V-MOS, 16V, ±0,5A, <1,5Ω(0,3A)	39b	Nec	BST 60, 2SK601, 2SK1078, 2SK1592
2SK1564	MOS-N-FET-e*	SMD, V-MOS, 30V, ±0,5A, <1,5Ω(0,3A)	39b	Nec	BST 80, 2SK601, 2SK1078, 2SK1592
2SK1565	MOS-N-FET-e*	SMD, V-MOS, 16V, ±1A, <1Ω(0,5A)	39b	Nec	2SK1726
2SK1568	MOS-N-FET-e*	SMD, V-MOS, 30V, ±1A, <0,6Ω(0,5A)	39b	Nec	2SK1726
2SK1567	MOS-N-FET-e*	SMD, V-MOS, 16V, ±2A, <0,5Ω(1A)	39a	Nec	2SK1311, 2SK1717
2SK1568	MOS-N-FET-e*	SMD, V-MOS, 16V, ±3A, <0,3Ω(1A)	39b	Nec	2SK2054
2SK1569	MOS-N-FET-e*	SMD, V-MOS, 100V, ±0,1A, <25Ω(10mA)	35a	Nec	BSS 123
2SK1590	MOS-N-FET-e*	SMD, V-MOS, 60V, ±0,2A, <3Ω(10mA)	35a	Nec	BST 82
2SK1591	MOS-N-FET-e*	SMD, V-MOS, 100V, ±0,2A, <6,5Ω(10mA)	35a	Nec	—
2SK1592	MOS-N-FET-e*	SMD, V-MOS, 60V, ±0,5A, <2Ω(0,5A)	39b	Nec	BST 80, 2SK601, 2SK1078
2SK1593	MOS-N-FET-e*	SMD, V-MOS, 100V, ±0,5A, <5Ω(0,5A)	39b	Nec	2SK1079, 2SK1728
2SK1594	MOS-N-FET-e*	V-MOS, LogL, 30V, ±20A, 30W, <45mΩ(10A)	17c	Nec	BUK545-50, 2SK943, 2SK1214, 2SK1345..46
2SK1595	MOS-N-FET-e*	V-MOS, LogL, 30V, ±30A, 35W, <0,03Ω(15A)	17c	Nec	2SK1262
2SK1596	MOS-N-FET-e*	V-MOS, LogL, 30V, ±40A, 35W, <0,02Ω(20A)	17c	Nec	2SK1257, 2SK1653, 2SK1952
2SK16	N-FET	Uni, ra, 15V, Idss=0,5..7mA, Up<5V	5a	Hit	FBFS 70, 2N3821, 2N4220, 2SK104, ++
2SK160	N-FET	SMD, VHF, 30V, Idss>0,5mA, Up<4,5V	35f	Nec	—
2SK1600	MOS-N-FET-e	V-MOS, 800V, 3A, 75W, <5Ω(1,5A)	17p	Tos	BUK 456-800, 2SK1456, 2SK1638
2SK1601	MOS-N-FET-e	=2SK1600: 900V, <6,4Ω(1,5A)	17p	Tos	BUK 456-1000, 2SK1456, 2SK1638
2SK1602	MOS-N-FET-e	=2SK1600: 2,8A, 40W	17c	Tos	2SK1356, 2SK1460
2SK1603	MOS-N-FET-e	=2SK1601: 2,5A, 40W	17c	Tos	2SK1356, 2SK1460
2SK1805	MOS-N-FET-e	V-MOS, S-L, 450V, 5A, 50W, <1,3Ω(3A)	17c	Mat	2SK1231 32, 2SK1351, 2SK1826..27, ++
2SK1606	MOS-N-FET-e	V-MOS, S-L, 450V, 8A, 50W, <0,75Ω(4A)	17c	Mat	2SK1352, 2SK1568..1567
2SK1607	MOS-N-FET-e	V-MOS, S-L, 450V, 13A, 120W, <0,45Ω(7A)	18p	Mat	BUZ 338, 2SK725, 2SK788, 2SK699, 2SK1745
2SK1606	MOS-N-FET-e	V-MOS, S-L, 500V, 5A, 50W, <1,7Ω(3A)	17c	Mat	2SK1232, 2SK1351, 2SK1627
2SK1609	MOS-N-FET-e	V-MOS, S-L, 500V, 8A, 50W, <1Ω(4A)	17c	Mat	2SK1352, 2SK1567, 2SK2117
2SK160A	N-FET	=2SK160: 50V	35f		—
2SK161	N-FET	FM/VHF, 18V, Idss>1mA, Up<4V	41d	Tos	2N5246, 2SK107
2SK1610	MOS-N-FET-e	V-MOS, S-L, 500V, 13A, 120W, <0,6Ω(7A)	18p	Mat	BUZ 338, 2SK725, 2SK788, 2SK699, 2SK1757
2SK1611	MOS-N-FET-e	V-MOS, S-L, 800V, 3A, 50W, <4Ω(2A)	17c	Mat	2SK1356, 2SK1460
2SK1612	MOS-N-FET-e	V-MOS, S-L, 900V, 3A, 50W, <5Ω(2A)	17c	Mat	2SK1356, 2SK1460
2SK1613	MOS-N-FET-e	V-MOS, S-L, 900V, 5A, 120W, <2,8Ω(3A)	18p	Mat	BUZ 350..381, 2SK685, 2SK727
2SK1614	MOS-N-FET-e	V-MOS, 900V, 8A, 120W, <1,7Ω(4A)	18p	Mat	2SK1120, 2SK1356, 2SK1502, 2SK1692, ++
2SK1615	GaAs-N-FET	SHF, 3,5V, 60mA, Idss=12..60mA, 12GHz	51(SGSD)	Hit	—
2SK1618	GaAs-N-FET	SHF, 3,5V, 70mA, Idss=12..70mA, 12GHz	52(SGSD)	Hit	—
2SK1617	GaAs-N-FET	SHF, 3,5V, 60mA, Idss=12..60mA, 12GHz	52(SGSD)	Hit	—
2SK1618(L,S)	MOS-N-FET-e*	V-MOS, 800V, 3A, 30W, <5Ω(1A)	79p	Hit	2SK1624
2SK1619	GaAs-N-FET	UHF, 3V, 0,06A, Idss=15..60mA, 12GHz	52(SGSD)	Hit	—
2SK162	N-FET	Uni, ra, 40V, Idss>5mA, Up<1,2V	7a	Nec	2SK147, 2SK151
2SK1620(L,S)	MOS-N-FET-e*	V-MOS, 150V, 10A, 50W, <0,15Ω(5A)	79p	Hit	2SK1638, 2SK1741
2SK1621(L,S)	MOS-N-FET-e*	V-MOS, 250V, 7A, 50W, <0,55Ω(4A)	79p	Hit	2SK1638
2SK1622(L,S)	MOS-N-FET-e*	V-MOS, LogL, 60V, 25A, 50W, <0,04Ω(15A)	79p	Hit	2SK1918
2SK1623(L,S)	MOS-N-FET-e*	V-MOS, 100V, 20A, 50W, <0,085Ω(10A)	79p	Hit	—
2SK1624(L,S)	MOS-N-FET-e*	V-MOS, 600V, 4A, 50W, <2,4Ω(2A)	79p	Hit	—
2SK1625(L,S)	MOS-N-FET-e*	V-MOS, 800V, 7A, 75W, <1,3Ω(4A)	79p	Hit	—

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2SK1626	MOS-N-FET-e*	=2SK1155: Iso, 35W	15c	Hit	2SK1231.32, 2SK1351, 2SK1608
2SK1627	MOS-N-FET-e*	=2SK1156: Iso, 35W	15c	Hit	2SK1232, 2SK1351, 2SK1608
2SK1628	MOS-N-FET-e*	V-MOS, 450V, 30A, 200W, <0,25Ω(15A)	47c	Hit	2SK1454, 2SK1519..20, 2SK1681, 2SK1629
2SK1629	MOS-N-FET-e*	=2SK1628: 500V, <0,27Ω(15A)	47c	Hit	2SK1520
2SK163	N-FET	Uni, ra, 50V, Idss>1mA, Up<1,2V	7a	Nec	2SK43, 2SK121, 2SK170, 2SK186..187,++
2SK1630	MOS-N-FET-e	V-MOS, S-L, 700V, 3A, 75W, <4,4Ω(2A)	17p	Mit	2SK1456, 2SK1600..01, 2SK1638, 2SK1793++
2SK1631	MOS-N-FET-e	=2SK1630: Iso, 35W	17c	Mit	2SK1356, 2SK1460, 2SK1995
2SK1632	MOS-N-FET-e	V-MOS, S-L, 700V, 5A, 100W, <2,3Ω(3A)	17p	Mit	2SK1457, 2SK1501, 2SK1639, 2SK1643, ++
2SK1632S	MOS-N-FET-e	=2SK1632:	30p		—
2SK1633	MOS-N-FET-e	=2SK1632: Iso, 45W	17c	Mit	2SK1608, 2SK1985
2SK1634	MOS-N-FET-e	=2SK1632: 150W	≈18p	Mit	2SK1341, 2SK1461, 2SK1760, 2SK1794
2SK1635	MOS-N-FET-e	V-MOS, S-L, 60V, 50A, 130W, <23mΩ(25A)	77p	Mat	2SK1223, 2SK1380
2SK1636(L,S)	MOS-N-FET-e*	V-MOS, 250V, 15A, 75W, <0,27Ω(8A)	79p	Hit	2SK2063
2SK1637	MOS-N-FET-e*	V-MOS, 600V, 4A, 35W, <2,4Ω(2A)	15c	Hit	2SK1118, 2SK1404
2SK1638	MOS-N-FET-e	V-MOS, S-L, 900V, 3A, 60W, <5,5Ω(2A)	17p	Hit	BUK456-1000, 2SK1456, 2SK1601, 2SK1793
2SK1639	MOS-N-FET-e	V-MOS, S-L, 900V, 4A, 75W, <4Ω(2A)	17p	Hit	2SK1119, 2SK1501, 2SK1639, 2SK1643
2SK1641	MOS-N-FET-e	V-MOS, 250V, 20A, 150W, <0,23Ω(10A)	18p	Tos	2SK623, 2SK901, 2SK944, 2SK1673..74
2SK1642	MOS-N-FET-e	V-MOS, 400V, 9A, 45W, <0,55Ω(5A)	17c	Tos	2SK1609
2SK1643	MOS-N-FET-e	V-MOS, 900V, 5A, 125W, <2,8Ω(2A)	17p	Tos	2SK1639, 2SK1501
2SK1646	GaAs-N-FET-d	SMD, SHF, 6V, 100mA, Idss>15mA, 12GHz	44	Sey	—
2SK1647(L,S)	MOS-N-FET-e*	V-MOS, 900V, 2A, 50W, <7Ω(1A)	79p	Hit	2SK2005
2SK1648(L,S)	MOS-N-FET-e*	V-MOS, 60V, 15A, 40W, <0,065Ω(8A)	79p	Hit	2SK1622, 2SK1918, 2SK2284
2SK1649	MOS-N-FET-e	V-MOS, 900V, 8A, 150W, <2,5Ω(3A)	18p	Tos	2SK1358, 2SK1502, 2SK1614, 2SK1795,++
2SK165	N-FET	Video-Camera, 15V, Idss>8mA, Up<3V	7e,7d	Mat	—
2SK1650	MOS-N-FET-e	V-MOS, 900V, 4A, 125W, <4,3Ω(1,5A)	18p	Tos	2SK727, 2SK794, 2SK1461, 2SK1760,++
2SK1651	MOS-N-FET-e	V-MOS, 500V, 8A, 60W, <1Ω(5A)	≈18c,p	Tos	2SK1206, 2SK1329, 2SK1696, 2SK1832
2SK1653	MOS-N-FET-e	V-MOS, LogL, 60V, 45A, 45W, <0,02Ω(20A)	17c	Tos	2SK1257, 2SK1952
2SK1654	MOS-N-FET	250V, 16A	17p	Mit	—
2SK1655	MOS-N-FET	300V, 16A	17p	Mit	—
2SK1656	MOS-N-FET-e*	V-MOS, S, 30V, ±0,1A, 0,25W, <25Ω(10mA)	40c	Nec	BS170, BSS98
2SK1657	MOS-N-FET-e*	=2SK1657: SMD	35a	Nec	BSS123
2SK1658	MOS-N-FET-e*	=2SK1657: SMD	35a(2mm)	Nec	—
2SK1659(L,S)	MOS-N-FET-e	V-MOS, S-L, 900V, 3A, 80W, <5Ω(1,5A)	30p	Fjd	2SK1528
2SK1660	MOS-N-FET-e	V-MOS, 450V, 10A, 80W, <0,65Ω		Fjd	—
2SK1661	MOS-N-FET-e	V-MOS, 200V, 20A, 80W, <0,17Ω		Fjd	—
2SK1662	MOS-N-FET-e	V-MOS, 700V, 3A, 40W, <5,5Ω		Fjd	—
2SK1663(L,S)	MOS-N-FET-e	V-MOS, S-L, 800V, 3A, 80W, <4Ω(1,5A)	30p	Fjd	2SK1510, 2SK1528
2SK1664	MOS-N-FET-e	V-MOS, S-L, 700V, ±2A, 30W, <0,6Ω(1A)	17c	Nec	BUK446-600, 2SK1142, 2SK1611, 2SK1634
2SK1665	MOS-N-FET-e*	V-MOS, LogL, 60V, 45A, 125W, <0,02Ω(20A)	18p	Hit	BUK539-60, 2SK1379, 2SK1297, 2SK1514
2SK1666	MOS-N-FET-e	=2SK1665: Iso, 60W	18c	Hit	2SK1298, 2SK1653
2SK1667	MOS-N-FET-e*	V-MOS, 250V, 7A, 50W, <0,55Ω(4A)	15c	Hit	2SK741, 2SK1319..20, 2SK1400
2SK1668	MOS-N-FET-e*	=2SK1667: Iso	15c	Hit	2SK1476, 2SK1568..69
2SK1669	MOS-N-FET-e*	FREDFET, 250V, 30A, 125W, <0,095Ω(15A)	18c	Hit	—
2SK1670	MOS-N-FET-e*	=2SK1669: Iso, 60W	16c	Hit	—
2SK1671	MOS-N-FET-e*	V-MOS, 250V, 30A, 125W, <0,095Ω(15A)	18c	Hit	2SK902, 2SK1675..78
2SK1672	MOS-N-FET-e	V-MOS, 500V, 1A, 10W, <7Ω, 40/65ns	30p	Shi	2SK560, 2SK1152, 2SK1327
2SK1673	MOS-N-FET-e	V-MOS, S-L, 250V, 24A, 200W, <0,17Ω(12A)	≈13c	Mit	—
2SK1674	MOS-N-FET-e	=2SK1673: 300V, <0,2Ω(12A)	≈18c	Mit	—
2SK1675	MOS-N-FET-e	V-MOS, S-L, 250V, 30A, 250W, <0,13Ω(15A)	≈18c	Mit	—
2SK1676	MOS-N-FET-e	=2SK1675: 300V, <0,15Ω(15A)	≈18c	Mit	—
2SK1677	MOS-N-FET-e	V-MOS, S-L, 450V, 16A, 200W, <0,39Ω(8A)	≈18c	Mit	2SK1409, 2SK1411
2SK1678	MOS-N-FET-e	=2SK1677: 500V, <0,47Ω(8A)	≈18c	Mit	2SK1411
2SK1679	MOS-N-FET-e	V-MOS, S-L, 450V, 20A, 250W, <0,3Ω(10A)	≈18c	Mit	2SK1409, 2SK1411
2SK168	N-FET	FM-VM/O, 30V, Idss>4mA, Up<3V	7f	Hit	BF410C
2SK1680	MOS-N-FET-e	=2SK1679: 500V, <0,35Ω(10A)	≈18c	Mit	2SK1411
2SK1681	MOS-N-FET-e	V-MOS, 500V, 30A, 300W, <0,23Ω	77p	Shi	2SK1629
2SK1682	N-FET	SMD, AM/FM, 30V, Idss=112mA, Up<4V	35t	Son	2SK374
2SK1683	MOS-N-FET-e	=2SK1536: Iso, 50W	18c	Shi	2SK1463
2SK1684	MOS-N-FET-e	=2SK1537: Iso, 55W	18c	Shi	2SK1463
2SK1685	MOS-N-FET-e	=2SK1538: Iso, 65W	18c	Shi	2SK1464
2SK1686	MOS-N-FET-e	=2SK1539: Iso, 70W	18c	Shi	—
2SK1687	GaAs-N-FET	UHF, X..Ku-Band, 4V, 60mA, 12GHz	51(SGSD)	Mat	—
2SK1688	GaAs-N-FET	UHF, X..Ku-Band, 4V, 60mA, 12GHz	51(SGSD)	Mat	—
2SK1689	GaAs-N-FET	UHF, X..Ku-Band, 6V, 70mA, 12GHz	51(SGSD)	Mat	—
2SK169	N-FET	NF, ra, 15V, 50mA, Idss<50mA	7	Mat	—
2SK1690	MOS-N-FET-e	V-MOS, S-L, 450V, 3A, 50W, <2,6Ω(1,5A)	30p	Sey	2SK1691

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2SK1691	MOS-N-FET-e	V-MOS, S-L, 450V, 5A, 60W, <1,4Ω(3A)	30p	Sav	—
2SK1692	MOS-N-FET-e	V-MOS, 900V, 7A, 150W, <2Ω(3,5A)	18p	Tos	2SK1342, 2SK1358, 2SK1614, 2SK1795, ++
2SK1693	MOS-N-FET-e	V-MOS, 500V, 8A, 60W, <0,85Ω, 60/120ns	17p	Shi	IRF640, IRF842, 2SK1496, 2SK1574, ++
2SK1694	MOS-N-FET-e	=2SK1693: Iso, 35W	15c	Shi	2SK1352, 2SK1587, 2SK1609, 2SK1805, ++
2SK1695	MOS-N-FET-e	V-MOS, 500V, 10A, 80W, <0,85Ω, 60/120ns	16p	Shi	2SK724, 2SK896, 2SK1488, 2SK1753, ++
2SK1696	MOS-N-FET-e	=2SK1695: Iso, 50W	18c	Shi	2SK1206, 2SK1329, 2SK1523
2SK1697	MOS-N-FET-e*	SMD, V-MOS, LogL, 60V, 0,5A, <1,7Ω(0,3A)	39j	Hit	2SK1079
2SK1696	MOS-N-FET-e*	SMD, V-MOS, LogL, 100V, 0,3A, <4,5Ω(0,2A)	39j	Hit	2SK1079
2SK1699	MOS-N-FET-e	V-MOS, S-L, 450V, 5A, 75W, <1,8Ω(3A)	17p	Mit	BUZ41A..42, 2SK893, 2SK1246, 2SK1751, ++
2SK1699S	MOS-N-FET-e	=2SK1699:	30p		—
2SK17	N-FET	Uni, ra, 20V, Idss=0,3..6,5mA, Up<6V	7e	Tos	BFS70, 2N3369, 2N3821, 2SK381, ++
2SK170	N-FET	Uni, ra, 40V, Idss>1mA, Up<1,5V	7a	Tos	2SK43, 2SK121, 2SK163, 2SK188..167, ++
2SK1700	MOS-N-FET-e	=2SK1699: Iso, 35W	17c	Mit	2SK1231..32, 2SK1351, 2SK1608, 2SK1626++
2SK1701	MOS-N-FET	450V, 8A	17p	Mit	—
2SK1702	MOS-N-FET	450V, 8A	17c(p)	Mit	—
2SK1703	MOS-N-FET-e	V-MOS, S-L, 500V, 5A, 75W, <2,4Ω(3A)	17p	Mit	BUZ41A..42, 2SK893, 2SK1246, 2SK1751, ++
2SK1703S	MOS-N-FET-e	=2SK1703:	30p		—
2SK1704	MOS-N-FET-e	=2SK1703: Iso, 35W	17c	Mit	2SK1232, 2SK1351, 2SK1608, 2SK1627, ++
2SK1705	MOS-N-FET	500V, 8A	17p	Mit	—
2SK1706	MOS-N-FET	500V, 8A	17c(p)	Mit	—
2SK1707	MOS-N-FET	600V, 4A	17p	Mit	—
2SK1708	MOS-N-FET	600V, 4A	17c(p)	Mit	—
2SK1709	MOS-N-FET	600V, 8A	17p	Mit	—
2SK171	N-FET	Dual, 20V, 60mA, Idss>5mA, Up<2V	7-SIP	Mit	—
2SK1710	MOS-N-FET	600V, 8A	17c(p)	Mit	—
2SK1716	MOS-N-FET-e*	V-MOS, LogL, 60V, 2A, 20W, <0,37Ω(1A)	≈15c	Tos	BUK541-100, 2SK1255
2SK1717	MOS-N-FET-e*	=2SK1716: SMD	35b	Tos	2SK1311
2SK1718	MOS-N-FET-e*	V-MOS, LogL, 60V, 8A, 25W, <0,11Ω(3A)	≈15c	Tos	BUK541-60, BUK542-100, 2SK1255, 2SK1260
2SK1719	MOS-N-FET-e*	V-MOS, LogL, 60V, 5A, 20W, <0,11Ω(2,5A)	30p	Tos	2SK1112, 2SK1804, 2SK1949
2SK1720	MOS-N-FET-e	V-MOS, 60V, 45A, 100W, <0,03Ω(25A)	30p	Tos	2SK1792
2SK1721	MOS-N-FET-e	V-MOS, 500V, 3A, 40W, <3Ω(1A), 30/80ns	30p	Tos	2SK1314, 2SK1541, 2SK2066, 2SK2181, ++
2SK1722	MOS-N-FET-e	V-MOS, 500V, 5A, 60W, <1,5Ω(2,5A)	30p	Tos	2SK1316, 2SK2067, 2SK2184
2SK1723	MOS-N-FET-e	V-MOS, 600V, 12A, 150W, <0,65Ω(8A)	16p	Tos	2SK1988
2SK1724	MOS-N-FET-e*	=2SK1725: SMD	39b	Say	2SK1485, 2SK1726
2SK1725	MOS-N-FET-e*	V-MOS, LogL, 30V, 1A, 1W, <0,75Ω(0,5A)	9c	Say	2SK1727, 2SK1733
2SK1726	MOS-N-FET-e*	=2SK1727: SMD, 1A	39b	Say	2SK1485, 2SK1726
2SK1727	MOS-N-FET-e*	V-MOS, LogL, 60V, 0,8A, 1W, <1,2Ω(0,4A)	9c	Say	2SK1729, 2SK1733
2SK1728	MOS-N-FET-e*	=2SK1729: SMD, 1A	39b	Say	2SK1334, 2SKJ1485
2SK1729	MOS-N-FET-e*	V-MOS, LogL, 100V, 0,5A, <3,5Ω(0,25A)	9c	Say	2SK2085
2SK173	MOS-N-FET-e	V-MOS-L, 210V, 10A, 95W	23e	Son	(BUZ35, 2SK401)
2SK1730	MOS-N-FET-e*	V-MOS, LogL, 30V, 1,8A, 1W, <0,3Ω(1A)	9c	Say	2SK1470, 2SK1717, 2SK1733
2SK1731	MOS-N-FET-e*	V-MOS, LogL, 30V, 3A, <0,14Ω(1,5A)	≈12b	Say	2SK1735
2SK1732	MOS-N-FET-e*	V-MOS, LogL, 30V, 4,5A, <0,085Ω(2,5A)	≈12b	Say	2SK1735
2SK1733	MOS-N-FET-e*	V-MOS, LogL, 60V, 1,5A, <0,45Ω(0,75A)	9c	Say	2SK1736
2SK1734	MOS-N-FET-e*	V-MOS, LogL, 60V, 2,5A, <0,22Ω(1,5A)	≈12b	Say	2SK1736
2SK1735	MOS-N-FET-e*	V-MOS, LogL, 60V, 4A, <0,09Ω(2A)	≈12b	Say	—
2SK1736	MOS-N-FET-e*	V-MOS, LogL, 100V, 1A, <0,95Ω(0,5A)	9c	Say	2SK2085
2SK1737	MOS-N-FET-e*	V-MOS, LogL, 100V, 1,8A, <0,4Ω(1A)	≈12b	Say	—
2SK1736	MOS-N-FET-e*	V-MOS, LogL, 100V, 3A, <0,17Ω(1,5A)	≈12b	Say	—
2SK1739	MOS-N-FET-e	V-MOS, UHF-L, PQ=90W(770MHz)		Tos	—
2SK1740	N-FET	SMD, 40V, 0,1A, Idss=40..75mA, Up<5V	35e	Say	—
2SK1741	MOS-N-FET-e	V-MOS, 100V, 10A, 40W, <0,16Ω(8A)	30p	Say	2SK1620, 2SK1636
2SK1745	MOS-N-FET-e	V-MOS, 500V, 18A, 150W, <0,36Ω(9A)	16p	Tos	2SK870, 2SK1170, 2SK1498, 2SK1500, ++
2SK1746	MOS-N-FET-e	V-MOS, 600V, 2A, 40W, <4Ω(1A), 23/60ns	30p	Tos	2SK1624, 2SK1980
2SK1747	N-FET	Dual, 40V, Idss=40..75mA, Up<5V		Say	—
2SK1746(Z)	MOS-N-FET-e*	V-MOS, LogL, 60V, ±6A, 20W, <0,11Ω(4A)	30p	Nec	2SK1472
2SK1749	MOS-N-FET-e	V-MOS, 60V, ±50A, 150W, <25mΩ(25A)	16p	Say	BUK539-60, 2SK1258, 2SK1379
2SK175	MOS-N-FET-e	V-MOS, 160V, 8A, 125W, 250/90ns, <1,7Ω	23e	Hit	2SK258, (BUZ33)
2SK1750	MOS-N-FET-e*	V-MOS, S-L, 450V, ±5A, 50W, <1,4Ω(2,5A)	17p	Nec	BUZ41A..42, 2SK552..53, 2SK893, 2SK1246
2SK1750Z..1751Z	MOS-N-FET-e*	=2SK1750: 51	30p		—
2SK1751	MOS-N-FET-e*	=2SK1750: 500V, <1,5Ω(2,5A)	17p	Nec	BUZ41A..42, 2SK553, 2SK693, 2SK1246, ++
2SK1752	MOS-N-FET-e*	V-MOS, S-L, 450V, ±10A, 100W, <0,9Ω(5A)	18p	Nec	2SK644, 2SK724, 2SK1488, 2SK1785, ++
2SK1753	MOS-N-FET-e*	=2SK1752: 500V, <1Ω(5A)	18p	Nec	2SK844, 2SK724, 2SK1488, 2SK1785, ++
2SK1754	MOS-N-FET-e	V-MOS, LogL, 50V, 10A, 45W, <0,09Ω(5A)	30p	Mit	2SK2414
2SK1758	MOS-N-FET-e*	V-MOS, S-L, 450V, ±15A, 120W, <0,5Ω(8A)	16p	Nec	2SK725, 2SK768, 2SK899, 2SK1610, 2SK1745
2SK1757	MOS-N-FET-e*	=2SK1758: 500V, <0,6Ω(8A)	18p	Nec	2SK725, 2SK768, 2SK899, 2SK1610, 2SK1745

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2SK1758	MOS-N-FET-e*	V-MOS, S-L, 600V, ±2A, 30W, <4,2Ω(1A)	17c	Nec	BUK445-600, 2SK1142, 2SK1834
2SK176	MOS-N-FET-e	=2SK175: 200V	23e	Hit	2SK258, (BUZ33)
2SK1760	MOS-N-FET-e*	V-MOS, S-L, 900V, ±5A, 100W, <4Ω(3A)	18p	Nec	2SK727, 2SK1341, 2SK1649..50, 2SK1794,++
2SK1761	MOS-N-FET-e*	V-MOS, 250V, 12A, 75W, <0,35Ω(6A)	17c	Hit	—
2SK1762	MOS-N-FET-e*	=2SK1761: Iso, 35W	15c	Hit	—
2SK1763(L,S)	MOS-N-FET-e*	V-MOS, LogL, 30V, 2,5A, 10W, <0,35Ω	79p	Hit	2SK974, 2SK1262
2SK1764	MOS-N-FET-e*	SMD, V-MOS, LogL, 60V, 2A, <0,45Ω(1A)	39j	Hit	2SK1311, 2SK1470, 2SK1717, 2SK2054, ++
2SK1766	MOS-N-FET-e	V-MOS, 250V, 10A, 40W, <0,6Ω(5A)	17c	Tos	2SK1036, 2SK1762
2SK1767	MOS-N-FET-e	V-MOS, 600V, 3,5A, 40W, <2,5Ω(2,5A)	17c	Hit	2SK1572, 2SK2144
2SK1766	MOS-N-FET-e	V-MOS, LogL, 60V, 12A, 15W, <0,07Ω(6A)	≈30c	Tos	—
2SK1769	MOS-N-FET-e	V-MOS, 600V, 2A, 15W, <4Ω(1A)	≈30c	Tos	—
2SK1770	MOS-N-FET-e	=2SK1205: Iso, 60W	≈18c	Hit	—
2SK1771	MOS-N-FET-e	SMD, V-MOS, FM/VHF, 12,5V, 30mA	44(SD-G)	Tos	—
2SK1772	MOS-N-FET-e*	SMD, V-MOS, LogL, 30V, 1A, <0,6Ω(0,5A)	39b	Hit	2SK1485, 2SK1726, 2SK1726
2SK1773	MOS-N-FET-e*	V-MOS, 1000V, 5A, 100W, <2Ω(3A)	18c	Hit	BUZ357..358, 2SK1120, 2SK1205, 2SK1359
2SK1774	MOS-N-FET-e	=2SK684: Iso, 60W	≈18c	Hit	2SK1464, 2SK1685
2SK1775	MOS-N-FET-e*	=2SK1342: Iso, 60W	16c	Hit	2SK1464, 2SK1665..66
2SK1776	MOS-N-FET-e*	V-MOS, LogL, 60V, 10A, 20W, <0,15Ω(5A)	17c	Hit	—
2SK1777	MOS-N-FET-e*	V-MOS, LogL, 60V, 15A, 25W, <85mΩ(6A)	17c	Hit	—
2SK1778	MOS-N-FET-e*	V-MOS, LogL, 60V, 10A, 25W, <25mΩ(5A)	17c	Hit	—
2SK1779	MOS-N-FET-e	V-MOS, 600V, 3A, 60W, <3,5Ω	30p	Tos	2SK1510, 2SK1859
2SK1784	MOS-N-FET-e*	V-MOS, S-L, 450V, ±12A, 100W, <0,6Ω(6A)	18p	Nec	2SK644, 2SK724, 2SK1488, 2SK1723, ++
2SK1785	MOS-N-FET-e*	=2SK1784: 500V, <0,7Ω(6A)	6p	Nec	2SK644, 2SK724, 2SK1466, 2SK1723, ++
2SK1792	MOS-N-FET-e*	V-MOS, LogL, 60V, 45A, 100W, <20mΩ(20A)	30p	Tos	—
2SK1793	MOS-N-FET-e*	V-MOS, S-L, 900V, ±3A, 75W, <7,5Ω(2A)	17p	Nec	BUK456-1000, 2SK1458, 2SK1601, 2SK1638+
2SK1793Z	MOS-N-FET-e*	=2SK1793:	30p		2SK1510
2SK1794	MOS-N-FET-e*	V-MOS, S-L, 900V, ±6A, 100W, <2,8Ω(3A)	18p	Nec	2SK1358, 2SK1614, 2SK1502, 2SK1692, ++
2SK1795	MOS-N-FET-e*	V-MOS, S-L, 900V, ±8A, 140W, <1,6Ω(4A)	18p	Nec	2SK1358, 2SK1614, 2SK1502, 2SK1692, ++
2SK1796	MOS-N-FET-e*	V-MOS, S-L, 900V, ±10A, 150W, <1,2Ω(5A)	18p	Nec	2SK1933
2SK18	N-FET	Dua, S/VHF, 40V, Idss>0,45mA, Up<3,5V	TO-60	Tos	—
2SK160	MOS-N-FET-e	V-MOS-L, 600V, 20A, 300W, 200/250ns	88e	old	—
2SK1803	MOS-N-FET-e	V-MOS, 900V, 6A, 100W, <1,7Ω(4A)	18c(p)	Mat	2SK1358, 2SK1614, 2SK1502, 2SK1692, ++
2SK1804	MOS-N-FET-e*	V-MOS, LogL, 100V, 5A, 20W, <0,28Ω(2,5A)	30c	Tos	2SK1474
2SK1805	MOS-N-FET-e	V-MOS, 500V, 7A, 45W, <0,85Ω(4A)	17c	Tos	2SK1352, 2SK1567, 2SK1609
2SK1806	N-FET	Uni, 30V, Idss=0,66mA, Up<2,5V		Say	—
2SK1607	MOS-N-FET-e*	V-MOS, 900V, 4A, 60W, <4Ω(2A)	17c	Tos	2SK1639, 2SK1643, 2SK1501
2SK1806	MOS-N-FET-e*	=2SK1607: Iso, 35W	15c	Tos	—
2SK1609	MOS-N-FET-e*	=2SK1404: 60W	17c	Hit	2SK1117, 2SK1402
2SK181	MOS-N-FET-e	=2SK160: 600V	88e	old	—
2SK1810	MOS-N-FET-e	V-MOS, 300V, 10A, 50W, <0,7Ω, 75/100ns	16p	Shi	BUZ325..326, 2SK634
2SK1811	MOS-N-FET-e	V-MOS, 300V, 20A, 100W, <0,35Ω, 140/160ns	18p	Shi	BUZ323, 2SK1401
2SK1812	MOS-N-FET-e	V-MOS, 300V, 30A, 120W, <0,23Ω, 190/240ns	18p	Shi	2SK888, 2SK1674
2SK1813	MOS-N-FET-e	V-MOS, 100V, 30A, 70W, <0,55Ω(20A)	30p	Say	—
2SK1814	MOS-N-FET-e	V-MOS, S-L, 60V, 20A, 45W, <70mΩ(10A)	17p	Fjd	BUK555-60, 2SK972, 2SK1115, 2SK1296
2SK1815	MOS-N-FET-e	V-MOS, S-L, 60V, 35A, 50W, <35mΩ(17,5A)	18c	Fjd	2SK1424, 2SK1435..36, 2SK1666
2SK1816	MOS-N-FET-e	100V, 5A, 20W		Fjd	—
2SK1817	MOS-N-FET-e	V-MOS, S-L, 100V, 20A, 40W, <60mΩ(10A)	17c	Fjd	2SK1307, 2SK1348..49
2SK1818	MOS-N-FET-e	V-MOS, S-L, 250V, 20A, 50W, <0,25Ω(10A)	17c	Fjd	—
2SK1819	MOS-N-FET-e	V-MOS, 450V, 5A, 35W, <1,5Ω(2,5A)	7c	Fjd	2SK1231..32, 2SK1606, 2SK2114..15,++
2SK182	MOS-N-FET-e	V-MOS-L, 600V, 60A, 1000W, 250/300ns		old	—
2SK1820(L,S)	MOS-N-FET-e	V-MOS, S-L, 500V, 6A, 80W, <1,6Ω(3A)	30p	Fjd	—
2SK1621	MOS-N-FET-e	V-MOS, S-L, 600V, 2A, 30W, <6,5Ω(1A)	17c	Fjd	BUK445-600, 2SK1142, 2SK1384
2SK1822	MOS-N-FET-e	V-MOS, LogL, 60V, 20A, 35W, <0,07Ω(10A)	17c	Fjd	2SK943, 2SK1214, 2SK1290, 2SK1345..46
2SK1623	MOS-N-FET-e	V-MOS, LogL, 60V, 50A, 80W, <17mΩ(25A)	18c	Fjd	2SK1298, 2SK1653, 2SK1666
2SK1624	MOS-N-FET-e*	SMD, V-MOS, LogL, 30V, ±0,1A, <8Ω(10mA)	35a(1,6mm)	Nec	—
2SK1625	MOS-N-FET-e*	V-MOS, +Di(S→G), 50V, 0,05A, <50Ω(10mA)	41c	Tos	—
2SK1826	MOS-N-FET-e*	=2SK1825: SMD	35a	Tos	—
2SK1627	MOS-N-FET-e*	=2SK1825: SMD	35a(2mm)	Tos	—
2SK1828	MOS-N-FET-e*	V-MOS, +Di(S→G), 20V, 0,05A, <40Ω(10mA)	35a	Tos	—
2SK1829	MOS-N-FET-e*	=2SK1828:	35a(2mm)	Tos	—
2SK183	MOS-N-FET-e	=2SK182: 600V		old	—
2SK1830	MOS-N-FET-e*	=2SK1828:	35a(1,6mm)	Tos	—
2SK1831	MOS-N-FET-e*	=2SK1181: Iso, 50W	18c	Hit	2SK1225, 2SK1206, 2SK1328..29, 2SK1696++
2SK1832	MOS-N-FET-e*	=2SK1162: Iso, 50W	18c	Hit	2SK1206, 2SK1329, 2SK1523, 2SK1696
2SK1833	MOS-N-FET-e	V-MOS, 500V, 2,5A, 40W, <4Ω(1,5A)	17c	Mat	BUK444-500, 2SK1758
2SK1834	MOS-N-FET-e	V-MOS, 800V, 2A, 40W, <7Ω(1A), 35/85ns	17c	Mat	BUK446-600, 2SK1142, 2SK1459, 2SK1611 ++

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2SK1835	MOS-N-FET-e	V-MOS, 1500V, 4A, 125W, <7Ω(2A)	16c	Hit	—
2SK1836	MOS-N-FET-e*	V-MOS, 450V, 50A, 250W, <0,1Ω(25A)	47c	Hit	2SK1521..22
2SK1837	MOS-N-FET-e*	=2SK1836: 500V, <0,11Ω(25A)	47c	Hit	2SK1522
2SK1838(L,S)	MOS-N-FET-e*	V-MOS, 250V, 1A, 10W, <8Ω(0,5A)	79p	Hit	2SK945, 2SK1195
2SK1839	MOS-N-FET-e	=2SK1841: SMD	35d(2mm)	Say	—
2SK184	N-FET	Uni, 50V, Idss>0,6mA, Up<1,5V	41a	Tos	2SK68, 2SK106
2SK1840	MOS-N-FET-e	=2SK1841: SMD	35t	Say	2SK1590
2SK1841	MOS-N-FET-e	V-MOS, LogL, 30V, 0,1A, 0,2W, <25Ω(10mA)	401	Say	2SK1398
2SK1842	N-FET	SMD, Sensor, 40V, Idss>30µA, Up<3V	35f	Mat	—
2SK1846	MOS-N-FET-e	V-MOS, 800V, 3A, 40W, <4Ω(2A), 40/140ns	30c	Mat	2SK1526, 2SK2005
2SK1847	MOS-N-FET-e	V-MOS, LogL, 30V, 0,5A, <0,75Ω(250mA)	35a	Say	—
2SK1848	MOS-N-FET-e	V-MOS, LogL, 60V, 0,4A, <1,2Ω(0,2A)	35a	Say	—
2SK1849	MOS-N-FET-e	V-MOS, LogL, 100V, 0,25A, <3,5Ω(0,15A)	35a	Say	—
2SK185	N-FET	Dual, 30V, Idss>0,9mA, Up<1,49V	7e+7a	Son	—
2SK1850	MOS-N-FET-e*	V-MOS, LogL, 60V, ±10A, <0,07Ω(5A)	76c	Nec	—
2SK1851	MOS-N-FET-e*	V-MOS, LogL, 60V, ±15A, <45mΩ(8A)	76c	Nec	—
2SK1852	MOS-N-FET-e*	V-MOS, LogL, 100V, ±10A, <0,15Ω(5A)	76c	Nec	—
2SK1853	MOS-N-FET-e*	V-MOS, LogL, 100V, ±15A, <0,06Ω(8A)	76c	Nec	—
2SK1854	MOS-N-FET-e	V-MOS, DC-DC, 400V, 8A, 40W, <1Ω(2,5A)	17c	Tos	2SK1231, 2SK1351, 2SK1608, 2SK1627,++
2SK1855	MOS-N-FET-e	V-MOS, 500V, 12A, 125W, <0,7Ω(8A)	18p	Tos	2SK696, 2SK1488, 2SK1753, 2SK1785,++
2SK1856	MOS-N-FET-e	V-MOS, 500V, 15A, 150W, <0,5Ω	18p	Tos	2SK899, 2SK1610, 2SK1745, 2SK1757,++
2SK1858	MOS-N-FET-e	V-MOS, S-L, 800V, 3A, 60W, <5Ω(1,5A)	30p	Tos	2SK1510, 2SK1659
2SK1859	MOS-N-FET-e*	=2SK1341: Iso, 60W	16c	Hit	2SK1464, 2SK1684..85, 2SK1775
2SK186	N-FET	Uni, ra, 40V, Idss>1,6mA, Up<1,5V	7a	Hit	2SK187, 2SK364, 2SK366
2SK1861	MOS-N-FET-e	V-MOS, 150V, 4A, 10W, <0,6Ω, 57/121ns	30p	Shi	—
2SK1862	MOS-N-FET-e*	=2SK1153: Iso, 25W	15c	Hit	BUK 445-450..-500, 2SK1572, 2SK1767,++
2SK1863	MOS-N-FET-e*	=2SK1154: Iso, 25W	15c	Hit	BUK 445-500, 2SK1572, 2SK1767,++
2SK1864	MOS-N-FET-e	V-MOS, 500V, 8A, 100W, <0,85Ω(4A)	30p	Tos	2SK1316, 2SK2187
2SK1865	MOS-N-FET-e	V-MOS, 500V, 12A, 100W, <0,7Ω(8A)	30p	Tos	2SK2366Z
2SK1867	MOS-N-FET-e	V-MOS, 900V, 2A, 15W, <4,85Ω(2A)	76c	Mat	(2SK1143, 2SK1275, 2SK1459)
2SK1868	MOS-N-FET-e	V-MOS, LogL, 60V, 3A, 15W, <0,2Ω(3A)	76c	Mat	(BUK541-60, 2SK1255)
2SK1869(LS)(A)	MOS-N-FET-e*	=2SK1400: 50W	79p	Hit	—
2SK187	N-FET	Uni, ra, 40V, Idss>2,5mA, Up<1,5V	7a	Hit	2SK186, 2SK364, 2SK366
2SK187	N-FET	=2SK190			—
2SK1871	MOS-N-FET-e	V-MOS, LogL, 60V, 15A, 40W, <60mΩ(10A)	30p	Say	2SK1648, 2SK1898, 2SK2322
2SK1872	MOS-N-FET-e	V-MOS, 50V, 25A, 40W, <40mΩ(12A)	17c	Tos	2SK943, 2SK1290, 2SK1420, 2SK1346, ++
2SK1875	MOS-N-FET-e	=2SK709: SMD	35f(2mm)	Tos	—
2SK1876	MOS-N-FET-e	V-MOS, 450V, 10A, 80W		Fjd	—
2SK1877	MOS-N-FET-e*	V-MOS, LogL, 60V, 10A, 12W, <75mΩ(5A)	14b	Hit	—
2SK1878	MOS-N-FET-e*	V-MOS, LogL, 100V, 10A, 12W, <0,14Ω(5A)	14b	Hit	—
2SK1879	MOS-N-FET-e	V-MOS, 60V, 45A, 125W, <0,03Ω(25A)	18p	Tos	BUK 439-60, 2SK649, 2SK657, 2SK1379, ++
2SK1880(L,S)	MOS-N-FET-e*	V-MOS, 600V, 1,5A, 20W, <8Ω(1A)	79p	Hit	(2SK1327)
2SK1881(L,S)	MOS-N-FET-e	V-MOS, LogL, 60V, 20A, 45W, <0,07Ω(10A)	30p	Fjd	2SK1919
2SK1882	MOS-N-FET-e	V-MOS, LogL, 60V, 25A, 40W, <0,05Ω(12A)	17c	Tos	2SK943, 2SK1095, 2SK1214, 2SK1345
2SK1883	MOS-N-FET-e	V-MOS, LogL, 30V, 18A, 50W, <0,055Ω(9A)	17p	Say	2SK942, 2SK972, 2SK1115, 2SK1910
2SK1884	MOS-N-FET-e	V-MOS, LogL, 30V, 22A, 60W, <0,04Ω(11A)	17p	Say	2SK942, 2SK972, 2SK1115, 2SK1910
2SK1885	MOS-N-FET-e	V-MOS, LogL, 30V, 35A, 70W, <25mΩ(18A)	17p	Say	2SK1291, 2SK1296
2SK1886	MOS-N-FET-e*	V-MOS, LogL, 30V, 15A, 25W, <55mΩ(9A)	17c	Say	2SK1094, 2SK1286
2SK1887	MOS-N-FET-e*	V-MOS, LogL, 30V, 20A, 25W, <40mΩ(11A)	17c	Say	2SK943, 2SK1290, 2SK1345, 2SK1348..49
2SK1888	MOS-N-FET-e*	V-MOS, LogL, 30V, 30A, 30W, <25mΩ(18A)	17c	Say	2SK943, 2SK1290, 2SK1345, 2SK1348..49
2SK1889	MOS-N-FET-e*	V-MOS, LogL, 30V, 18A, 50W, <55mΩ(9A)	30p	Say	2SK1848, 2SK1896
2SK1890	MOS-N-FET-e*	V-MOS, LogL, 30V, 22A, 60W, <40mΩ(11A)	30p	Say	2SK1622
2SK1891	MOS-N-FET-e*	V-MOS, LogL, 30V, 35A, 70W, <25mΩ(18A)	30p	Say	2SK1900
2SK1892	MOS-N-FET-e	V-MOS, LogL, 60V, 15A, 50W, <80mΩ(8A)	17p	Say	BUK552-60, 2SK942, 2SK1115..18, 2SK1347
2SK1893	MOS-N-FET-e	V-MOS, LogL, 60V, 18A, 60W, <70mΩ(9A)	17p	Say	BUK552-60, 2SK942, 2SK1115..16, 2SK1347
2SK1894	MOS-N-FET-e	V-MOS, LogL, 60V, 30A, 70W, <40mΩ(15A)	17p	Say	2SK1291, 2SK1296
2SK1895	MOS-N-FET-e*	V-MOS, LogL, 60V, 12A, 25W, <60mΩ(8A)	17c	Say	2SK1093, 2SK1258, 2SK1305..06, 2SK1344++
2SK1896	MOS-N-FET-e*	V-MOS, LogL, 60V, 15A, 25W, <70mΩ(9A)	17c	Say	2SK943, 2SK1214, 2SK1345
2SK1897	MOS-N-FET-e*	V-MOS, LogL, 60V, 25A, 30W, <0,04Ω(15A)	17c	Say	2SK943, 2SK1095, 2SK1214, 2SK1345
2SK1898	MOS-N-FET-e*	V-MOS, LogL, 60V, 15A, 50W, <60mΩ(8A)	30p	Say	2SK1648
2SK1899	MOS-N-FET-e*	V-MOS, LogL, 60V, 8A, 60W, <70mΩ(9A)	30p	Say	2SK1622
2SK19(TM)	N-FET	FM/VHF, 18V, Idss=3..24mA, Up=3V	7d	Tos,Mic	BFS71, BFS60, BFW11, 2N3822, 2N4416++
2SK190	N-FET	NF, re, 40V, 0,2A, Idss>6mA, Up<1,5V	7a(9mm)	Hit	—
2SK1900	MOS-N-FET-e*	V-MOS, LogL, 60V, 30A, 70W, <40mΩ(15A)	30p	Say	—
2SK1901	MOS-N-FET-e	V-MOS, LogL, 100V, 12A, 50W, <0,16Ω(8A)	17p		2SK1300..01, 2SK1559, 2SK1561
2SK1902	MOS-N-FET-e	V-MOS, LogL, 100V, 15A, 60W, <135mΩ(7A)	17p		2SK1301, 2SK1559, 2SK1551

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2SK1903	MOS-N-FET-e	V-MOS, LogL, 100V, 25A, 70W, <80mΩ(12A)	17p		2SK1116, 2SK1302, 2SK1347
2SK1904	MOS-N-FET-e*	V-MOS, LogL, 100V, 10A, 25W, <0,16Ω(6A)	17c		BUK545-100, 2SK1305, 2SK1035
2SK1905	MOS-N-FET-e*	V-MOS, LogL, 100V, 12A, 25W, <135mΩ(7A)	17c	Say	2SK1034, 2SK1288, 2SK1306
2SK1906	MOS-N-FET-e*	V-MOS, LogL, 100V, 20A, 30W, <0,08Ω(12A)	17c	Say	2SK1292, 2SK1307, 2SK1348..49
2SK1907	MOS-N-FET-e*	V-MOS, LogL, 100V, 12A, 50W, <0,16Ω(6A)	30p	Say	2SK1623
2SK1908	MOS-N-FET-e*	V-MOS, LogL, 100V, 15A, 80W, <135mΩ(7A)	30p	Say	2SK1623
2SK1909	MOS-N-FET-e*	V-MOS, LogL, 100V, 25A, 70W, <80mΩ(12A)	30p	Say	—
2SK191	N-FET	NF, 15V, 0,5A, Idss>10mA, Up<3V	7a(9mm)	Hit	—
2SK1910	MOS-N-FET-e*	V-MOS, LogL, 60V, 25A, 50W, <0,04Ω(15A)	17p	Hit	2SK942, 2SK972, 2SK1115
2SK1911	MOS-N-FET-e*	V-MOS, LogL, 80V, 40A, 75W, <22mΩ(20A)	17p	Hit	2SK1542
2SK1913	MOS-N-FET-e	V-MOS, 600V, 4A, 40W, <1,8Ω(2,5A)	17c	Tos	2SK1118, 2SK1637
2SK1914	MOS-N-FET-e	V-MOS, 600V, 1,5A, 15W, <6,5Ω(0,75A)	≈30p	Tos	—
2SK1915	MOS-N-FET-e	V-MOS, 600V, 6A, 100W, <1,25Ω(3A)	30p	Tos	—
2SK1916	MOS-N-FET-e	V-MOS, S-L, 450V, 18A, 80W, <0,45Ω(6A)	18c	Fjd	2SK1406, 2SK1453, 2SK1525
2SK1917M	MOS-N-FET-e	V-MOS, 250V, 10A, 50W, <0,4Ω(5A)	17c	Fjd	2SK528, 2SK1036
2SK1918(L,S)	MOS-N-FET-e*	=2SK1910	30p	Hit	2SK1622
2SK1919(L,S)	MOS-N-FET-e*	=2SK1911	30p	Hit	2SK1792
2SK192(A)	N-FET	FM/VHF, 18V, Idss>3mA, Up<3V	41d	Tos	BF410B..C
2SK1920	MOS-N-FET-e*	V-MOS, S-L, 250V, 4A, 30W, <0,7Ω(2A)	30c	Say	—
2SK1921	MOS-N-FET-e*	V-MOS, S-L, 250V, 4A, 50W, <0,7Ω(2A)	17p	Say	2SK477, 2SK741, 2SK924, 2SK1391
2SK1922	MOS-N-FET-e	V-MOS, 600V, 2A, 50W, <4,3Ω(1A)	17p	Say	BUZ80, 2SK858, 2SK1323..24
2SK1923	MOS-N-FET-e	V-MOS, S-Reg, 600V, 4A, 60W, <1,8Ω(2A)	17p	Say	2SK1402, 2SK1501, 2SK1639, 2SK1643
2SK1924	MOS-N-FET-e	V-MOS, S-Reg, 600V, 6A, 70W, <1,5Ω(3A)	17p	Say	2SK1117, 2SK1643
2SK1925	MOS-N-FET-e	V-MOS, S-Reg, 600V, 6A, 120W, <1,2Ω(4A)	18p	Say	BUZ332A, 2SK1032
2SK1926	MOS-N-FET-e	V-MOS, 80V, 15A, 50W, <0,1Ω	17c	Tos	2SK943, 2SK1214, 2SK1345
2SK1927	MOS-N-FET-e	V-MOS, 100V, 15A, 60W, <0,18Ω(6A)	30p	Tos	2SK1623
2SK1928	MOS-N-FET-e	V-MOS, 100V, 27A, 80W, <85mΩ(15A)	30p	Tos	—
2SK1929	MOS-N-FET-e	V-MOS, 900V, 5A, 100W, <2,8Ω(2A)	30p	Tos	2SK1528, 2SK2006
2SK193	N-FET	FM, 20V, Idss>0,5mA, Up<2,5V	40f	Nec	BF410A, 2SK195, 2SK212
2SK1930	MOS-N-FET-e	V-MOS, 1000V, 4A, 80W, <3,8Ω(2A)	30p	Tos	—
2SK1931	MOS-N-FET-e	V-MOS, 200V, 5A, 20W, <0,65Ω, 55/75ns	30p	Shi	—
2SK1933	MOS-N-FET-e*	V-MOS, 900V, 10A, 150W, <1,2Ω(5A)	18c	Hit	2SK1796
2SK1934	MOS-N-FET-e*	V-MOS, 1000V, 8A, 150W, <1,6Ω(4A)	16c	Hit	2SK1120
2SK1936-01	MOS-N-FET-e	V-MOS, 500V, 10A, 100W, <0,76Ω(5A)	18p	Fjd	2SK644, 2SK724, 2SK1488, 2SK1785, ++
2SK1937-01	MOS-N-FET-e	V-MOS, 500V, 15A, 125W, <0,48Ω(7,5A)	18p	Fjd	2SK725, 2SK788, 2SK899, 2SK1610, 2SK1745
2SK1938-01	MOS-N-FET-e	V-MOS, 500V, 16A, 100W, <0,35Ω(9A)	16c	Fjd	2SK1406, 2SK1525
2SK1939-01	MOS-N-FET-e	V-MOS, 600V, 6A, 100W, <1,2Ω(4A)	18p	Fjd	BUZ332A, 2SK1032
2SK194	N-FET	Dual, 40V, 50mA, Idss>5mA, Up<1,2V	7e+7a	Nec	—
2SK1940-01	MOS-N-FET-e	V-MOS, 600V, 12A, 125W, <0,75Ω(8A)	18p	Fjd	BUZ334, 2SK1723
2SK1941-01	MOS-N-FET-e	V-MOS, 600V, 16A, 100W, <0,55Ω(6A)	18c	Fjd	2SK1405
2SK1942-01	MOS-N-FET-e	V-MOS, 900V, 3A, 80W, <4Ω(1,5A)	18p	Fjd	2SK696, 2SK726..727, 2SK794, 2SK1341, ++
2SK1943-01	MOS-N-FET-e	V-MOS, 900V, 5A, 80W, <2,8Ω(2,5A)	17p	Fjd	2SK1457, 2SK1501, 2SK1639, 2SK1643
2SK1944-01	MOS-N-FET-e	V-MOS, 900V, 5A, 100W, <2,8Ω(2,5A)	18p	Fjd	2SK727, 2SK794, 2SK1341, 2SK1780, ++
2SK1945-01	MOS-N-FET-e	V-MOS, 900V, 5A, 80W, <2,8Ω(2,5A)	16c	Fjd	2SK1463, 2SK1684, 2SK1859
2SK1946-01M	MOS-N-FET-e	V-MOS, 60V, 45A, 50W, <22mΩ(22,5A)	17c	Fjd	2SK1257, 2SK1653, 2SK1952
2SK1947	MOS-N-FET-e*	FREDFET, 250V, 50A, 200W, <60mΩ(25A)	47c	Hit	—
2SK1948	MOS-N-FET-e*	V-MOS, 250V, 50A, 200W, <80mΩ(25A)	47c	Hit	—
2SK1949(L,S)	MOS-N-FET-e*	V-MOS, LogL, 60V, 5A, 20W, <0,15Ω(3A)	30p	Hit	2SK1112, 2SK1471, 2SK1719
2SK195	N-FET	FM, 20V, Idss>0,5mA, Up<2,5V	7t	Nec	BF410A, 2SK193, 2SK212, 2SK606
2SK1950(L,S)	MOS-N-FET-e*	V-MOS, LogL, 80V, 3A, 10W, <0,23Ω(2A)	30p	Hit	2SK974, 2SK1282, 2SK1254, 2SK1299, ++
2SK1951	MOS-N-FET-e*	=2SK1910: Iso, 35W	17c	Hit	2SK943, 2SK1095, 2SK1345..46, 2SK1307, ++
2SK1952	MOS-N-FET-e*	=2SK1911: Iso, 35W	17c	Hit	2SK1257, 2SK1653
2SK1953	MOS-N-FET-e*	V-MOS, S-L, 600V, ±2A, 25W, <5Ω(1A)	17c	Nec	BUK445-600, 2SK1142, 2SK1834
2SK1954(Z)	MOS-N-FET-e	V-MOS, S-L, 180V, ±4A, 20W, <0,65Ω(2A)	30p	Nec	2SK1920
2SK1957	MOS-N-FET-e*	V-MOS, 200V, 7A, 30W, <0,45Ω(4A)	15c	Hit	BUK545-200, 2SK1568..69, 2SK1668
2SK1958	MOS-N-FET-e*	SMD, V-MOS, LogL, 16V, ±0,1A, <12Ω(10m)	35a(mm)	Nec	—
2SK1959	MOS-N-FET-e*	SMD, V-MOS, LogL, 16V, ±2A, <0,5Ω(1A)	39b	Nec	2SK1311, 2SK1470, 2SK1717
2SK196	MOS-N-FET-e	V-MOS, 160V, 0,5A, 0,8W, <15Ω, 20/30ns	2e(S=case)	Hit	BSS93
2SK1960	MOS-N-FET-e*	SMD, V-MOS, LogL, 16V, ±3A, <0,2Ω(1,5A	39b	Nec	2SK2054
2SK1961	N-FET	VHF/UHF, 15V, Idss=40..75mA, Up<4,5V	7e	Say	—
2SK1962	GaAs-N-FET	UHF, 4V, 80mA, Idss>12mA, 12GHz	51(SGSD)	Mat	—
2SK1963	GaAs-N-FET	UHF, 4V, 80mA, Idss>12mA, 12GHz	51(SGSD)	Mat	—
2SK1964	GaAs-N-FET	UHF, 4V, 60mA, Idss>12mA, 12GHz	51(SGSD)	Mat	—
2SK1967	MOS-N-FET-e	V-MOS, LogL, 80V, 20A, 45W, <0,07Ω(10A)	30c	Mat	2SK1622, 2SK1918
2SK1968	MOS-N-FET-e*	V-MOS, 600V, 12A, 100W, <0,88Ω(6A)	18c	Hit	BUZ334, 2SK1723
2SK1969-01	MOS-N-FET-e	V-MOS, LogL, 80V, 50A, 125W, <17mΩ(25A)	18p	Fjd	BUK539-60, 2SK1258, 2SK1379..80

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2SK197	N-FET	SMD, VHF, 18V, Idss>2mA, Up<4V	35c	Hit	2SK210, 2SK217
2SK1971	MOS-N-FET-e*	V-MOS, 500V, 35A, 200W, <0,23Ω(18A)	47c	Hit	2SK1520, 2SK1629
2SK1973(F5)	MOS-N-FET-e	V-MOS, 60V, 2A, 20W, <0,35Ω(1A)	30c	Rhm	2SK462, 2SK973, 2SK1763
2SK1974	MOS-N-FET-e	V-MOS, 60V, 10A, 30W, <0,35Ω(1A)	17c	Rhm	BUK442-60, 2SK1093, 2SK1256, 2SK1344
2SK1975	MOS-N-FET-e	V-MOS, 450V, 10A, 80W, <0,35Ω(1A)	16c(p)	Rhm	2SK724, 2SK899, 2SK1488, 2SK1757, ++
2SK1976	MOS-N-FET-e	V-MOS, 450V, 5A, 30W, <1,4Ω(1A)	17c	Rhm	2SK1231..32, 2SK1606, 2SK1626..27, ++
2SK198	MOS-N-FET-e	SMD, NF, ra, 30V, 20mA, Idss>0,5mA	35f	Mat	—
2SK1981-01	MOS-N-FET-e	V-MOS, S-L, 500V, 10A, 60W, <0,76Ω(5A)	17p	Fjd	2SK1503
2SK1962-01M	MOS-N-FET-e	=2SK1981: Iso, 50W	17c	Fjd	2SK1351, 2SK1606, 2SK1627
2SK1983-01	MOS-N-FET-e	V-MOS, S-L, 900V, 3A, 60W, <4Ω(1,5A)	17p	Fjd	BUK456-1000, 2SK1601, 2SK1638, 2SK1793
2SK1964-01M	MOS-N-FET-e	=2SK1963: Iso	17c	Fjd	2SK1356, 2SK1460
2SK1965-01M	MOS-N-FET-e	V-MOS, 900V, 5A, 50W, <2,8Ω(2,5A)	17c	Fjd	2SK1608
2SK1966-01	MOS-N-FET-e	V-MOS, 1000V, 4A, 60W, <3,6Ω(2A)	17p	Fjd	2SK1119
2SK1987	MOS-N-FET-e	V-MOS, S-L, 250V, ±7A, 30W, <0,5Ω(4A)	17c	Nec	2SK1478, 2SK1588..69, 2SK1668
2SK1988	MOS-N-FET-e*	V-MOS, 450V, ±2,5A, 30W, <2,8Ω(1,5A)	17c	Nec	BUK444-450, 2SK1833
2SK1989	MOS-N-FET-e*	=2SK1988: 500V, <3Ω(1,5A)	17c	Nec	BUK444-500, 2SK1833
2SK199	N-FET	SMD, HF, 15V, Idss<12mA	35c	Mat	—
2SK1990	MOS-N-FET-e*	V-MOS, 450V, ±4,5A, 30W, <1,4Ω(2,5A)	17c	Nec	2SK1351, 2SK1445, 2SK1608, 2SK1626..27++
2SK1991	MOS-N-FET-e*	=2SK1990: 500V, <1,5Ω(2,5A)	17c	Nec	2SK1351, 2SK1232, 2SK1808, 2SK1627, ++
2SK1992	MOS-N-FET-e*	V-MOS, 450V, ±6A, 35W, <0,9Ω(3A)	17c	Nec	2SK1352, 2SK1566..67, 2SK1609, 2SK1605++
2SK1993	MOS-N-FET-e*	=2SK1992: 500V, <1Ω(3A)	17c	Nec	2SK1352, 2SK1567, 2SK1609, 2SK1605, ++
2SK1994	MOS-N-FET-e*	V-MOS, 900V, ±2A, 30W, <7,5Ω(1A)	17c	Nec	2SK1143, 2SK1174, 2SK1275
2SK1995	MOS-N-FET-e*	V-MOS, 900V, ±3A, 35W, <4Ω(2A)	17c	Nec	2SK1356, 2SK1460
2SK1996	GaAs-N-FET-d	SHF, 3V, 60mA, Idss=15..60mA, 12GHz	51(SGSD)	Tos	—
2SK1997	MOS-N-FET-e	V-MOS, LogL, 50V, 36A, 40W, <0,03Ω(18A)	17c	Tos	2SK1257, 2SK1653, 2SK1952
2SK1996	MOS-N-FET-e	V-MOS, LogL, 60V, 45A, 125W, <0,03Ω(20A)	18p	Tos	BUK539-60, 2SK1379, 2SK1297, 2SK1514
2SK1999	MOS-N-FET-e*	V-MOS, Dual, 120V, 12A, PO>150W(200MHz)	≈	Hit	—
2SK2002-01M	MOS-N-FET-e	V-MOS, 600V, 3A, 30W, <4,5Ω(1,5A)	17c	Fjd	2SK1572, 2SK2144
2SK2003-01M	MOS-N-FET-e	V-MOS, 600V, 4A, 40W, <2,4Ω(2A)	17c	Fjd	2SK1118, 2SK1404
2SK2004-01L,S	MOS-N-FET-e	V-MOS, 1000V, 4A, 60W, <3,6Ω(2A)	30p	Fjd	—
2SK2005	MOS-N-FET-e	V-MOS, 900V, 3A, 50W, <5Ω, 45/110ns	30c	Shi	2SK1510
2SK2006	MOS-N-FET-e	V-MOS, 900V, 5A, 65W, <3Ω, 65/145ns	30c	Shi	2SK1528
2SK2007	MOS-N-FET-e*	V-MOS, 250V, 20A, 100W, <0,15Ω(10A)	16c	Hit	2SK901, 2SK944, 2SK1641, 2SK2056
2SK2006	MOS-N-FET-e*	=2SK2007: Iso, 60W	16c	Hit	2SK1406, 2SK1525, 2SK1870
2SK2009	MOS-N-FET-e*	SMD, V-MOS, 30V, 0,2A, <2Ω(50mA)	35a	Tos	—
2SK201	GaAs-N-FET	UHF, C232C..X-Band, 10V, 400mA, 8GHz	52(SGSD)	Nec	—
2SK2010	MOS-N-FET-e*	V-MOS, 250V, 4A, 25W, <0,7Ω(2A)	17c	Say	2SK1478, 2SK1568..69, 2SK1668, 2SK1987
2SK2011	MOS-N-FET-e*	V-MOS, 250V, 12A, 30W, <0,35Ω(8A)	17c	Say	2SK1036, 2SK1762
2SK2012	MOS-N-FET-e*	V-MOS, 250V, 18A, 40W, <0,16Ω(12A)	17c	Say	—
2SK2013	MOS-N-FET-e	V-MOS, 180V, 1A, 25W	17c	Tos	2SK528..529
2SK2014	MOS-N-FET-e	V-MOS, LogL, 100V, 1A, 10W, <0,95Ω(0,5A)	30c	Mat	—
2SK2015	MOS-N-FET-e	V-MOS, LogL, 150V, 3A, 10W, <1,1Ω(2A)	30c	Mat	—
2SK2016	MOS-N-FET-e	V-MOS, LogL, 100V, 5A, 10W, <0,47Ω(3A)	30c	Mat	2SK1474, 2SK1804
2SK2017	MOS-N-FET-e	V-MOS, 550V, 1A, 10W, <6Ω(0,6A)	30c	Mat	2SK1327, 2SK1660
2SK2018-01(L,S)	MOS-N-FET-e	V-MOS, LogL, 60V, 10A, 20W, <0,1Ω(5A)	30p	Fjd	2SK2414
2SK2019-01	MOS-N-FET-e	V-MOS, S-L, 500V, 3,5A, 40W, <3Ω(1,5A)	17p	Fjd	2SK1154, 2SK1244
2SK2020-01M	MOS-N-FET-e	=2SK2019: Iso, 30W	17c	Fjd	BUK445-500, 2SK1572, 2SK1767, ++
2SK2021-01	MOS-N-FET-e	V-MOS, 500V, 5A, 60W, <1,8Ω(2,5A)	17p	Fjd	BUZ41A42, 2SK553, 2SK893, 2SK1246, ++
2SK2022-01M	MOS-N-FET-e	=2SK2021: Iso, 40W	17c	Fjd	2SK1232, 2SK1351, 2SK1608, 2SK1627
2SK2023-01	MOS-N-FET-e	V-MOS, 500V, 3A, 50W, <4,5Ω(1,5A)	17p	Fjd	BUK456-800, 2SK1800
2SK2024-01	MOS-N-FET-e	=2SK2023:	18p	Fjd	BUZ307, BUZ360..361, 2SK603
2SK2025-01	MOS-N-FET-e	V-MOS, 600V, 4A, 60W, <2,4Ω(2A)	17p	Fjd	BUZ90, 2SK1117, 2SK1402, 2SK1809, ++
2SK2026-01	MOS-N-FET-e	=2SK2025:	18p	Fjd	2SK695, 2SK793, 2SK1213, 2SK1403
2SK2027-01	MOS-N-FET-e	V-MOS, 600V, 8A, 80W, <1,2Ω(4A)	17p	Fjd	BUK657-600, BUZ91, BUZ305
2SK2028-01M	MOS-N-FET-e	=2SK2027: Iso, 50W	17c	Fjd	—
2SK2029-01(L,S)	MOS-N-FET-e	V-MOS, S-L, 900V, 3A, 60W, <4Ω(1,5A)	30p	Fjd	2SK1510, 2SK1528
2SK203	GaAs-N-FET	UHF, C..X-Band, 10V, 160mA, 8GHz	52(SGSD)	Nec	—
2SK2030	MOS-N-FET-e	V-MOS, S-L, 60V, 5A, 20W, <0,14Ω(2,5A)	30p	Tos	2SK1112, 2SK1471, 2SK1719
2SK2032	MOS-N-FET-e	V-MOS, 450V, 13A, 100W, <0,45Ω(7A)	16c(p	Mat	2SK899, 2SK1676, 2SK1745, 2SK1757
2SK2033	MOS-N-FET-e	V-MOS, +Di(S→G), 20V, 0,1A, <12Ω(10mA)	35a	Tos	—
2SK2034	MOS-N-FET-e	=2SK2033:	35a(2	Tos	—
2SK2035	MOS-N-FET-e	=2SK2033:	35e(l	Tos	—
2SK2036	MOS-N-FET-e	V-MOS, +Di(S→G), 20V, 0,1A, <6Ω(10mA)	35a	Tos	—
2SK2037	MOS-N-FET-e	=2SK2036:	35a(2	Tos	—
2SK2036	MOS-N-FET-e	V-MOS, 600V, 5A, 125W, <2,2Ω(3A)	18p	Tos	2SK727, 2SK1341, 2SK1649..50, 2SK1794, ++
2SK2039	MOS-N-FET-e	V-MOS, 900V, 5A, 150W, <2,5Ω(3A)	18p	Tos	2SK727, 2SK1341, 2SK1649..50, 2SK1794, ++

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2SK2040(Z)	MOS-N-FET-e*	V-MOS, 900V, ±2A, 20W, <5Ω(1A)	30p	Nec	—
2SK2041	MOS-N-FET-e	V-MOS, LogL, 60V, 10A, 60W, <95mΩ(5A)	30p	Rhm	2SK1907
2SK2042	MOS-N-FET-e	V-MOS, S-L, 450V, 5A, 60W, <1,4Ω(2,5A)	30p	Rhm	2SK1691
2SK2043(LS)	MOS-N-FET-e	V-MOS, 600V, 2A, 25W, <4,3Ω(1A)	17c	Say	BUK445-600, 2SK1142, 2SK1834
2SK2044(LS)	MOS-N-FET-e	V-MOS, 600V, 4A, 30W, <2,4Ω(2A)	17c	Say	2SK1116, 2SK1404, 2SK1637
2SK2045(LS)	MOS-N-FET-e	V-MOS, 600V, 5,5A, 35W, <1,5Ω(3A)	17c	Say	2SK1116, 2SK1404
2SK2046	MOS-N-FET-e	V-MOS, LogL, 30V, 12A, 30W, <0,05Ω(4A)	30p	Say	2SK1754, 2SK2018, 2SK2414
2SK2047	MOS-N-FET-e	V-MOS, 550V, 1,2A, 15W, <8Ω(0,6A)	≈30c	Mat	—
2SK2048-01(L,S)	MOS-N-FET-e	V-MOS, 30V, 35A, 60W, <22mΩ(17,5A)	30p	Fjd	2SK1919
2SK2049	MOS-N-FET-e	V-MOS, LogL, 60V, 50A, 60W, <25mΩ(25A)	17p	Fjd	BUK556-60, 2SK1542
2SK2050	MOS-N-FET-e	V-MOS, LogL, 100V, 30A, 60W, <55mΩ(15A)	17p	Fjd	2SK1293
2SK2051-01(L,S)	MOS-N-FET-e	V-MOS, 250V, 10A, 80W, <0,4Ω(5A)	30p	Fjd	2SK1636
2SK2052	MOS-N-FET-e	V-MOS, 500V, 10A, 60W, <1,1Ω(5A)	16c	Fjd	2SK1206, 2SK1329, 2SK1523
2SK2053	MOS-N-FET-e*	SMD, V-MOS, LogL, 16V, ±5A, <0,12Ω(2,5A)	39b	Nec	—
2SK2054	MOS-N-FET-e*	SMD, V-MOS, LogL, 60V, ±3A, <0,2Ω(1,5A)	39b	Nec	—
2SK2055	MOS-N-FET-e*	SMD, V-MOS, LogL, 100V, ±2A, <0,35Ω(1A)	39b	Nec	2SK1473
2SK2056	MOS-N-FET-e	V-MOS, 600V, 4A, 40W, <2,4Ω(2A)	17c	Tos	2SK1605
2SK2057	MOS-N-FET-e	V-MOS, 500V, 20A, 150W, <0,31Ω(12A)	16p	Tos	2SK1170, 2SK1411, 2SK1560
2SK2058	MOS-N-FET-e*	V-MOS, S-L, 250V, 25A, 120W, <0,16Ω(12A)	18p	Say	2SK901, 2SK944, 2SK1641, 2SK1673..74
2SK2059(L,S)	MOS-N-FET-e*	V-MOS, 600V, 3A, 20W, <5Ω(2A)	78p	Hit	—
2SK2062	MOS-N-FET-e	V-MOS, 250V, 10A, 50W, <0,5Ω, 75/100ns	30c	Shi	2SK1636
2SK2063	MOS-N-FET-e	V-MOS, 250V, 20A, 60W, <0,25Ω, 140/160ns	30c	Shi	—
2SK2064	MOS-N-FET-e	V-MOS, 300V, 10A, 50W, <0,7Ω, 75/100ns	30c	Shi	—
2SK2065	MOS-N-FET-e	V-MOS, 300V, 20A, 60W, <0,35Ω, 140/160ns	30c	Shi	—
2SK2066	MOS-N-FET-e	V-MOS, 500V, 3A, 40W, <2,3Ω, 45/75ns	30c	Shi	2SK1314, 2SK1721
2SK2067	MOS-N-FET-e	V-MOS, 500V, 5A, 50W, <1,4Ω, 50/90ns	30c	Shi	2SK1314, 2SK1541, 2SK1722
2SK2068	MOS-N-FET-e	V-MOS, 500V, 8A, 60W, <0,65Ω, 60/120ns	30c	Shi	2SK1316, 2SK2167
2SK2069	MOS-N-FET-e	V-MOS, 500V, 10A, 60W, <0,7Ω, 70/143ns	30c	Shi	2SK2167
2SK2070	MOS-N-FET-e*	V-MOS, LogL, 100V, ±1,5A, <0,35Ω(1A)	9c	Nec	—
2SK2071-01(L,S)	MOS-N-FET-e	V-MOS, 600V, 2A, 20W, <6,5Ω(1A)	30p	Fjd	—
2SK2072-01(L,S)	MOS-N-FET-e	V-MOS, 600V, 6A, 60W, <2,1Ω(3A)	≈30p	Fjd	—
2SK2073	N-FET	=2SK2074: SMD	35t	Say	—
2SK2074	N-FET	AM-Tuner, 15V, Idss>6mA, Up<1,2V	40e	Say	—
2SK2075	MOS-N-FET-e*	V-MOS, 250V, 20A, 100W, <0,13Ω(10A)	16c	Hit	2SK901, 2SK944, 2SK1641, 2SK2007, ++
2SK2076	N-FET	SMD, Uni, 30V, Idss>0,4mA, Up<1,5V	35e,l	Say	—
2SK2077	MOS-N-FET-e	V-MOS, 600V, 7A, 150W, <1,7Ω(3,5A)	18p	Tos	2SK1342, 2SK1356, 2SK1502, 2SK1795
2SK2078	MOS-N-FET-e	V-MOS, 600V, 9A, 150W, <1,2Ω(4A)	18p	Tos	2SK1796, 2SK1933
2SK206	N-FET	SMD, NF-V, 50V, Idss>0,3mA, Up<5V	35l	Tos	—
2SK2080-01	MOS-N-FET-e	V-MOS, 500V, 15A, 60W, <0,55Ω(8A)	16c	Fjd	2SK1269, 2SK1331, 2SK1405, 2SK1524
2SK2081-01	MOS-N-FET-e	V-MOS, 500V, 12A, 125W, <0,6Ω(6A)	18p	Fjd	BUZ339, 2SK1610, 2SK1745, 2SK1785
2SK2082-01	MOS-N-FET-e	V-MOS, 900V, 9A, 150W, <1,4Ω(4,5A)	16p	Fjd	2SK1358, 2SK1614, 2SK1502, 2SK1692, ++
2SK2083	MOS-N-FET-e	V-MOS, 900V, 5A, 70W, <3,6Ω(2A)	30p	Say	2SK1526
2SK2084(L,S)	MOS-N-FET-e*	V-MOS, LogL, 20V, 7A, 20W, <53mΩ(4A)	79p	Hit	2SK1472, 2SK1748
2SK2085	MOS-N-FET-e*	V-MOS, LogL, 100V, 1A, 0,9W, <0,9Ω(0,5A)	5c	Hit	2SK1736
2SK2088	MOS-N-FET-e	V-MOS, 200V, 10A, 58W, <0,4Ω(5A)	30p	Tos	2SK1636
2SK2089	MOS-N-FET-e	V-MOS, 600V, 5A, 100W, <2,4Ω(3A)	30p	Tos	—
2SK209	N-FET	SMD, Uni, 50V, Idss>0,6mA, Up<1,5V	35l	Tos	2SK94, 2SK425
2SK2090	MOS-N-FET-e*	SMD, V-MOS, LogL, 50V, ±0,1A, <20Ω(10mA)	35a(2mm)	Nec	—
2SK2091	N-FET	=2SK2076:	35a(2mm)	Say	—
2SK2094(L,S)	MOS-N-FET-e	V-MOS, LogL, 60V, 2A, 20W, <0,35Ω(1A)	30p	Rhm	2SK973, 2SK1763
2SK2095	MOS-N-FET-e	V-MOS, LogL, 60V, 10A, 30W, <95mΩ(5A)	17c	Rhm	2SK1093, 2SK1256, 2SK1305..06, 2SK1344++
2SK2096	MOS-N-FET-e*	V-MOS, LogL, 60V, 45A, 100W, <22mΩ(25A)	16c	Hit	2SK1297, 2SK1514, 2SK1665
2SK2097	MOS-N-FET-e*	V-MOS, 600V, 4A, 35W, <2,4Ω(2A)	15c	Hit	2SK1116, 2SK1404, 2SK1637
2SK2098-01M	MOS-N-FET-e	V-MOS, LogL, 150V, 20A, 50W, <60mΩ(10A)	17c	Fjd	2SK1266
2SK2099-01(L,S)	MOS-N-FET-e	V-MOS, 250V, 8A, 20W, <0,85Ω(3A)	30p	Fjd	2SK1920
2SK210	N-FET	SMD, FM/VHF, 18V, Idss>3mA, Up<3V	35c	Tos	2SK217
2SK2100	MOS-N-FET-e	V-MOS, 600V, 4A, 40W, <3,3Ω(2A)	17c	Fjd	2SK1808
2SK2101-01	MOS-N-FET-e	V-MOS, 600V, 6A, 50W, <2,1Ω(3A)	17c	Fjd	—
2SK2103	MOS-N-FET-e	SMD, V-MOS, LogL, 30V, 2A, <0,4Ω(1A)	39b	Rhm	2SK1311, 2SK1470, 2SK1717
2SK2104(F5)	MOS-N-FET-e	V-MOS, LogL, 60V, 5A, 20W	30p	Rhm	2SK1471, 2SK1719, 2SK1949
2SK2106	MOS-N-FET-e	V-MOS, LogL, 60V, 5A, 30W	17c	Rhm	BUK541-60, 2SK705, 2SK1255, 2SK1260, ++
2SK2107	MOS-N-FET-e	V-MOS, 200V, 20A, 100W, <0,16Ω(10A)	30p	Tos	—
2SK2108	MOS-N-FET-e*	V-MOS, LogL, 250V, 6A, 25W, <0,5Ω(3A)	17c	Say	2SK1476, 2SK1566..69, 2SK1666, 2SK1967
2SK2109	MOS-N-FET-e*	SMD, V-MOS, LogL, 60V, ±0,5A, <0,6Ω(0,3A)	39b	Nec	2SK1079, 2SK1697
2SK211	N-FET	SMD, FM/VHF, 16V, Idss>1mA, Up<4V	35c	Tos	2SK197
2SK2110	MOS-N-FET-e*	SMD, V-MOS, LogL, 100V, ±0,5A, <1,2Ω(0,3A)	39b	Nec	2SK1079, 2SK1728

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2SK2111	MOS-N-FET-e*	SMD, V-MOS, LogL, 60V, ±1A, <0,45Ω(0,5A)	39b	Nec	2SK1485, 2SK1726, 2SK1728
2SK2112	MOS-N-FET-e*	SMD, V-MOS, LogL, 100V, ±1A, <0,8Ω(0,5A)	39b	Nec	2SK1485, 2SK1728
2SK2113	GaAs-N-FET-d	SMD, UHF, 3V, Idss=12..60mA, Up<2,5V	44(SDSG)	Nec	—
2SK2114	MOS-N-FET-e*	V-MOS, 450V, 5A, 35W, <1,4Ω(2,5A)	15c	Hit	2SK1231..32, 2SK1351, 2SK1608, 2SK1626++
2SK2115	MOS-N-FET-e*	=2SK2114: 500V, <1,5Ω(2,5A)	15c	Hit	2SK1232, 2SK1351, 2SK1608, 2SK1827,++
2SK2116	MOS-N-FET-e*	V-MOS, 450V, 7A, 35W, <0,8Ω(4A)	15c	Hit	2SK1352, 2SK1566 67, 2SK1609, 2SK1605++
2SK2117	MOS-N-FET-e*	=2SK2116: 500V, <0,9Ω(4A)	15c	Hit	2SK1352, 2SK1567, 2SK1805
2SK2118	MOS-N-FET-e*	V-MOS, 600V, 5A, 35W, <1,5Ω(2,5A)	15c	Hit	2SK1118, 2SK1404, 2SK1637, 2SK2097,++
2SK2119	MOS-N-FET-e*	=2SK1910: Iso, 30W	17c	Hit	2SK943, 2SK1095, 2SK1345 46, 2SK1307,++
2SK212	N-FET	FM, 20V, Idss>0,6mA, Up<2,5V	40d	Say	BF410A, 2N5484
2SK2120	MOS-N-FET-e*	=2SK1911: Iso, 35W	17c	Hit	2SK1257, 2SK1653
2SK2121	MOS-N-FET-e*	V-MOS, LogL, 60V, 50A, 100W, <10mΩ(25A)	18p	Hit	BUK539-60, 2SK1258, 2SK1379
2SK2122	MOS-N-FET-e	=2SK1478	17c	Mat	→2SK1478
2SK2123	MOS-N-FET-e	=2SK1605	17c	Mat	→2SK1605
2SK2124	MOS-N-FET-e	=2SK1606	17c	Mat	→2SK1606
2SK2125	MOS-N-FET-e	=2SK1833	17c	Mat	→2SK1833
2SK2126	MOS-N-FET-e	=2SK1606	17c	Mat	→2SK1608
2SK2127	MOS-N-FET-e	=2SK1609	17c	Mat	→2SK1609
2SK2128	MOS-N-FET-e	=2SK1834	17c	Mat	→2SK1834
2SK2129	MOS-N-FET-e	=2SK1848	17c	Mat	2SK1356, 2SK1460
2SK213	MOS-N-FET-e*	V-MOS, 140V, 0,5A, 30W, 8Ω, 20/30ns	17d	Hit	—
2SK2130	MOS-N-FET-e	=2SK1612	17c	Mat	→2SK1612
2SK2131	MOS-N-FET-e*	V-MOS, 150V, ±15A, 35W, <0,12Ω(8A)	17c	Nec	2SK1350
2SK2132	MOS-N-FET-e*	V-MOS, 160V, ±4A, 1,8W, <0,65Ω(2A)	78c	Nec	—
2SK2133	MOS-N-FET-e	V-MOS, 250V, ±16A, 75W, <0,26Ω(8A)	17p	Nec	BUZ255
2SK2133Z	MOS-N-FET-e	=2SK2133:	30p		2SK1636
2SK2134	MOS-N-FET-e	V-MOS, 200V, ±13A, 70W, <0,4Ω(7A)	17p	Nec	BUK456-200, BUZ255, IRF640, IRF642
2SK2135	MOS-N-FET-e	V-MOS, 200V, ±14A, 35W, <0,18Ω(7A)	17c	Nec	2SK1350
2SK2136	MOS-N-FET-e	V-MOS, 200V, ±20A, 75W, <0,18Ω(10A)	17p	Nec	BUZ30A
2SK2137	MOS-N-FET-e	V-MOS, 600V, ±4A, 30W, <2,4Ω(2A)	17c	Nec	2SK1118, 2SK1404, 2SK1637
2SK2138	MOS-N-FET-e	V-MOS, 600V, ±5A, 70W, <2,4Ω(2,5A)	17p	Nec	2SK1117, 2SK1402, 2SK1609
2SK2139	MOS-N-FET-e	V-MOS, 600V, ±5A, 35W, <1,5Ω(2,5A)	17c	Nec	2SK1118, 2SK1404, 2SK1637
2SK214	MOS-N-FET-e*	=2SK213: 160V	17d	Hit	—
2SK2140	MOS-N-FET-e	V-MOS, 600V, ±7A, 75W, <1,5Ω(3,5A)	17p	Nec	BUK657-600, BUZ91, BUZ305
2SK2141	MOS-N-FET-e	V-MOS, 600V, ±6A, 35W, <1,1Ω(3A)	17c	Nec	2SK1118, 2SK1404
2SK2142	MOS-N-FET-e	V-MOS, LogL, 250V, 12A, 70W, <0,35Ω	17p	Say	(BUZ255, 2SK2133)
2SK2144	MOS-N-FET-e*	=2SK2059: Iso, 25W	15c	Hit	2SK1572, 2SK1767
2SK2145	N-FET	SMD, Dual, 50V, Idss=1,2..14mA, Up<1,5V	45	Tos	—
2SK2148	MOS-N-FET-e	V-MOS, 250V, 2A, 25W, <2Ω(1A)	17c	Tos	—
2SK2147	MOS-N-FET-e	V-MOS, 900V, 6A, 80W, <2,8Ω(3A)	18c	Fjd	2SK1176, 2SK1464, 2SK1685, 2SK1859
2SK2148	MOS-N-FET-e	V-MOS, 600V, 12A, 80W, <0,75Ω(6A)	18c	Fjd	2SK1405
2SK2149	MOS-N-FET-e	V-MOS, 500V, 10A, 125W, <2Ω(1A)	18p	Tos	2SK724, 2SK1488, 2SK1753, 2SK1785,++
2SK215	MOS-N-FET-e*	=2SK213: 160V	17d	Hit	—
2SK2150	MOS-N-FET-e	V-MOS, 500V, 15A, 150W, <0,4Ω(7A)	18p	Tos	BUZ338, 2SK899, 2SK1516, 2SK1610,++
2SK2151	MOS-N-FET-e	SMD, V-MOS, LogL, 20V, 1A, <0,48Ω(0,5A)	39b	Say	2SK1485, 2SK1726, 2SK1728
2SK2152	MOS-N-FET-e	SMD, V-MOS, LogL, 20V, 2A, <0,18Ω(1A)	39b	Say	2SK1311, 2SK1470, 2SK1717
2SK2153	MOS-N-FET-e	V-MOS, LogL, 20V, 4A, 20W, <90mΩ	30p	Say	2SK1059, 2SK1112, 2SK1471, 2SK1719
2SK2154	MOS-N-FET-e	V-MOS, LogL, 20V, 12A, 30W, <42mΩ(6A)	30p	Say	—
2SK2157	MOS-N-FET-e	SMD, V-MOS, LogL, 30V, ±5A, <0,1Ω(2,5A)	39b	Nec	—
2SK2158	MOS-N-FET-e*	SMD, V-MOS, LogL, 50V, ±0,1A, <15Ω(10mA)	35a	Nec	2SK1590..91
2SK2159	MOS-N-FET-e*	SMD, V-MOS, LogL, 60V, ±2A, <0,3Ω(1A)	39b	Nec	2SK1311, 2SK1470, 2SK1717
2SK216	MOS-N-FET-e*	=2SK213: 200V	17d	Hit	—
2SK2160	MOS-N-FET-e	V-MOS, LogL, 200V, 7A, 25W, <0,45Ω(3,5A)	17c	Say	BUK545-200
2SK2181	MOS-N-FET-e	V-MOS, LogL, 200V, 8A, 25W, <0,35Ω(4,5A)	17c	Say	—
2SK2162	MOS-N-FET-e	V-MOS, 180V, 1A, 20W, <5Ω(0,6A)	30p	Tos	2SK1195, 2SK1836
2SK2163	MOS-N-FET-e	V-MOS, LoaL, 60V, 40A, 40W, <20mΩ(22A)	17c	Say	2SK1257, 2SK1653, 2SK1952
2SK2184	MOS-N-FET-e	V-MOS, LogL, 60V, 45A, 70W, <20mΩ(22A)	30p	Say	2SK1919
2SK2165	MOS-N-FET-e	V-MOS, LogL, 60V, 40A, 100W, <0,03Ω(20A)	18p	Fjd	BUK539-60, 2SK1379, 2SK1297, 2SK1514
2SK2166	MOS-N-FET-e	=2SK2165: Iso, 80W	18c	Fjd	2SK1298, 2SK1666
2SK2167	MOS-N-FET-e	SMD, V-MOS, 250V, 0,4A, <12Ω(0,2A)	39b	Say	—
2SK2168	MOS-N-FET-e	SMD, V-MOS, 250V, 0,8A, <5Ω(0,4A)	39b	Say	—
2SK2169	MOS-N-FET-e	V-MOS, 250V, 0,4A, <5Ω(0,2A)	9c	Say	—
2SK217	N-FET	SMD, VHF, 30V, Idss>2,5mA, Up<2,5V	35c	Hit	2SK210, 2SK217
2SK2170	N-FET	SMD, 30V, 20mA, Idss=1,2..4,5mA	35a(1,6mm)	Say	—
2SK2171	N-FET	SMD, 40V, 100mA, Idss=40..75mA	39b	Say	—
2SK2173	MOS-N-FET-e	V-MOS, LogL, 60V, 50A, 125W, <17mΩ(25A)	18p	Tos	BUK539-60, 2SK1258, 2SK1379

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2SK2174(L,S)	MOS-N-FET-e*	V-MOS, 500V, 20A, 120W, <0,27Ω(10A)	≈30c	Hit	—
2SK2175	MOS-N-FET-e*	V-MOS, LogL, 60V, 15A, 30W, <0,13Ω(8A)	17p	Hit	BUK552-60, 2SK971..72, 2SK1115, 2SK1910
2SK2176	MOS-N-FET-e	V-MOS, 500V, 5A, 30W, <1,5Ω(2,5A)	17c	Rhm	2SK1231..32, 2SK1351, 2SK1608
2SK2177	MOS-N-FET-e	V-MOS, 500V, 1A, 10W, <7Ω, 35/60ns	30p	Shi	2SK560, 2SK1152, 2SK1672, 2SK2017,++
2SK2178	MOS-N-FET-e	V-MOS, 500V, 2A, 15W, <4Ω, 40/70ns	30p	Shi	—
2SK2179	MOS-N-FET-e	V-MOS, 500V, 3A, 20W, <2,3Ω, 45/90ns	30p	Shi	2SK2059
2SK218	N-FET	Video-Camera, 15V, 50mA, Idss>5mA	7d	Met	—
2SK2160	MOS-N-FET-e	V-MOS, 500V, 3A, 40W, <2,3Ω, 45/90ns	17p	Shi	2SK1154, 2SK1244, 2SK1494
2SK2181	MOS-N-FET-e	=2SK2160:	30c	Shi	2SK1314, 2SK1721, 2SK2066
2SK2182	MOS-N-FET-e	=2SK2180: Iso, 25W	17c	Shi	BUK445-500, 2SK1863, 2SK1572, 2SK1767++
2SK2183	MOS-N-FET-e	V-MOS, 500V, 5A, 50W, <1,5Ω, 55/100ns	17p	Shi	BUZ41..42, IRF830, 2SK893, 2SK1246,++
2SK2184	MOS-N-FET-e	=2SK2183:	30c	Shi	2SK1314, 2SK1541, 2SK1722, 2SK2067
2SK2185	MOS-N-FET-e	=2SK2160: Iso, 30W	17c	Shi	2SK1232, 2SK1351, 2SK1608, 2SK2115,++
2SK2186	MOS-N-FET-e	V-MOS, 500V, 10A, 60W, <1Ω, 70/140ns	17p	Shi	2SK1503
2SK2187	MOS-N-FET-e	=2SK2186:	30c	Shi	2SK2069
2SK2186	MOS-N-FET-e	=2SK2186: Iso, 40W	17c	Shi	—
2SK2189	MOS-N-FET-e	-2SK2186: 70W	16p	Shi	2SK724, 2SK896, 2SK1488, 2SK753,++
2SK2160	MOS-N-FET-e	=2SK2186: Iso, 40W	18c	Shi	2SK1206, 2SK1329, 2SK1523, 2SK1696,++
2SK2191	MOS-N-FET-e	V-MOS, 500V, 12A, 60W, <0,7Ω, 90/190ns	30c	Shi	—
2SK2192	MOS-N-FET-e	=2SK2191: 50W	18p	Shi	2SK899, 2SK1678, 2SK1745, 2SK1757
2SK2193	MOS-N-FET-e	=2SK2186: Iso, 50W	18c	Shi	2SK1269, 2SK1331, 2SK1524
2SK2194	MOS-N-FET-e	V-MOS, 500V, 15A, 110W, <0,45Ω, 110/270ns	16p	Shi	2SK725, 2SK899, 2SK1610, 2SK1745,++
2SK2195	MOS-N-FET-e	=2SK2194: Iso, 60W	18c	Shi	2SK1269, 2SK1331, 2SK1524
2SK2196	MOS-N-FET-e	V-MOS, 500V, 20A, 125W, <0,35Ω, 135/340ns	16p	Shi	2SK870, 2SK1170, 2SK1411, 2SK1496,++
2SK2197	MOS-N-FET-e	=2SK2196 Iso, 70W	18c	Shi	2SK1406, 2SK1525
2SK2198	MOS-N-FET-e	V-MOS, 500V, 30A, 220W, <0,23Ω, 200/500ns	77p	Shi	2SK1520, 2SK1629, 2SK1971
2SK2199	MOS-N-FET-e	V-MOS, 250V, 0,8A, 15W, <5Ω(0,4A)	30p	Sey	2SK1638
2SK22	MOS-N-FET				—
2SK220	MOS-N-FET-e	V-MOS, 160V, 8A, 100W, <1,5Ω, 25/45ns	23e	Hit	2SK258, (BUZ33)
2SK2200	MOS-N-FET-e	V-MOS, LogL, 100V, 3A, 20W, <0,35Ω(2A)	30p	Tos	2SK1113, 2SK1254, 2SK1284, 2SK1299
2SK2201	MOS-N-FET-e	=2SK2200:	30p	Tos	→2SK2200
2SK2202	MOS-N-FET-e*	V-MOS, LogL, 120V, 7A, 20W, <0,4Ω(4A)	15c	Hit	BUK545-200, 2SK1957
2SK2203	MOS-N-FET-e*	=2SK2121: Iso, 80W	18c	Hit	2SK1298, 2SK1424, 2SK1666
2SK2204(L,S)	MOS-N-FET-e*	=2SK2205:	30p	Hit	2SK1792, 2SK1919
2SK2205	MOS-N-FET-e*	V-MOS, LogL, 30V, 45A, 75W, <15mΩ(25A)	17p	Hit	2SK1542, 2SK1911
2SK2206	MOS-N-FET-e*	=2SK2205: Iso, 35W	17c	Hit	2SK1257, 2SK1853, 2SK1952
2SK2207	MOS-N-FET-e	V-MOS, 900V, ±3A, 35W, <5Ω(1,5A)		Sak	—
2SK2208	MOS-N-FET-e	V-MOS, 900V, ±5A, 75W, <3Ω(2,5A)		Sak	—
2SK221	MOS-N-FET-e	=2SK220: 200V	23e	Hit	2SK258, (BUZ33)
2SK2212	MOS-N-FET-e*	V-MOS, 200V, 10A, 30W, <0,3Ω(5A)	15c	Hit	2SK526, 2SK1036, 2SK1762
2SK2213-01(L,S)	MOS-N-FET-e	V-MOS, 500V, 10A, 80W, <0,76Ω(5A)	30p	Fjd	2SK2366Z
2SK2215-01(L,S)	MOS-N-FET-e	V-MOS, 600V, 8A, 80W, <1,2Ω(4A)	30p	Fjd	—
2SK2216	MOS-N-FET-e	V-MOS, UHF-L, 60V, 20A, PQ=150W(860MHz		Hit	—
2SK2217	MOS-N-FET-e	V-MOS, UHF-L, 60V, 10A, PQ=60W(860MHz)		Hit	—
2SK2218	N-FET	SMD, 15V, 100mA, Idss=4075mA	39b	Say	—
2SK2219	N-FET	SMD, Kondens-Mikrofon, 20V	35a(2mm)	Say	—
2SK222	N-FET	Uni, ra, 40V, Idss>0,6mA, Up=0,5V	7e	Say	2SK68, 2SK102, 2SK184
2SK2220	MOS-N-FET-e*	V-MOS, NF-L, 160V, 8A, 100W, 250/90ns	18d	Hit	—
2SK2221	MOS-N-FET-e*	=2SK2220: 200V	18d	Hit	—
2SK2222	MOS-N-FET-e	V-MOS, LogL, 600V, 5A, 80W, <2,2Ω(3A)	16c(p)	Tos	—
2SK2223	MOS-N-FET-e	V-MOS, 500V, 10A, 60W, <0,78Ω(5A)	18c	Fjd	2SK1206, 2SK1329, 2SK1523, 2SK1696
2SK2224	MOS-N-FET-e	V-MOS, 900V, 3A, 50W, <4Ω(1,5A)	18c	Fjd	2SK809A, 2SK1463, 2SK1864
2SK2225	MOS-N-FET-e*	V-MOS, 1500V, 2A, 50W, <12Ω(1A)	16c	Hit	—
2SK2227	MOS-N-FET-e	V-MOS, 800V, 4A, 60W, <2,4Ω	30p	Sey	—
2SK2228	MOS-N-FET-e	V-MOS, LogL, 60V, 5A, <0,11Ω(2,5A)	≈12c	Tos	(2SK1112, 2SK1471, 2SK1719, 2SK1949)
2SK2229	MOS-N-FET-e	V-MOS, LogL, 60V, 5A, <0,11Ω(2,5A)	≈12c	Tos	(2SK1112, 2SK1471, 2SK1719)
2SK223	N-FET	NF-Tr, 80V, Idss>1,2mA, Up=0,75V	7e	Say	—
2SK2230	MOS-N-FET-e	V-MOS, 250V, 2A, 1,2W, <2Ω(1A)	≈12c	Tos	—
2SK2231	MOS-N-FET-e	V-MOS, LogL, 60V, 5A, 20W, <0,18Ω(2,5A)	30p	Toe	2SK1112, 2SK1471, 2SK1719
2SK2232	MOS-N-FET-e	V-MOS, LogL, 60V, 25A, 35W, <46mΩ(12A)	17c	Tos	2SK1095, 2SK1214, 2SK1345, 2SK1697
2SK2233	MOS-N-FET-e	V-MOS, LogL, 60V, 45A, 100W, <30mΩ(25A)	16p	Toe	2SK1297, 2SK1514, 2SK1665, 2SK2096
2SK2234	MOS-N-FET-e	V-MOS, 500V, ±8A, 40W, <0,6Ω(4A)	17c	Nec	2SK1352, 2SK1587, 2SK1809, 2SK1805
2SK2235	MOS-N-FET-e	V-MOS, 250V, 2A, 20W, <2Ω(1,5A)	30p	Tos	—
2SK2238	MOS-N-FET-e	V-MOS, 500V, 5A, 40W, <1,6Ω(2,5A)	17c	Tos	2SK1232, 2SK1351, 2SK1608, 2SK1827,++
2SK2237	MOS-N-FET-e	V-MOS, 500V, 7A, 45W, <0,8Ω(4A)	17c	Tos	2SK1352, 2SK1587, 2SK1605
2SK2247	MOS-N-FET-e*	SMD, V-MOS, LogL, 60V, ±2A, <0,35Ω(1A)	39j	Hit	2SK1311, 2SK1717, 2SK1763

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2SK225	MOS-N-FET-e	V-MOS, 120V, 7A, 100W, <1,7Ω, 180/60ns	20d	Hit	(2SK343..344)
2SK2250-01 (L,S)	MOS-N-FET-e	V-MOS, 250V, 2A, 10W, <2Ω(1A)	30p	Fjd	—
2SK2251-01	MOS-N-FET-e	V-MOS, 250V, 2A, 20W, <2Ω(1A)	17p	Fjd	2SK923
2SK2252-01 (L,S)	MOS-N-FET-e	V-MOS, 250V, 8A, 50W, <0,5Ω(4A)	30p	Fjd	2SK1621
2SK2253-01M	MOS-N-FET-e	V-MOS, 250V, 8A, 20W, <0,5Ω(4A)	17c	Fjd	2SK1476, 2SK1568..89, 2SK1888
2SK2254-01 (L,S)	MOS-N-FET-e	V-MOS, 250V, 18A, 80W, <0,18Ω(9A)	30p	Fjd	2SK2063
2SK2255-01M	MOS-N-FET-e	=2SK2254: Iso	17c	Fjd	2SK2012
2SK2256-01	MOS-N-FET-e	=2SK2254:	17p	Fjd	—
2SK2257-01	MOS-N-FET-e	V-MOS, 500V, 17A, 150W, <0,4Ω(9A)	18p	Fjd	2SK725, 2SK788, 2SK899, 2SK1810, 2SK1745
2SK2258-01	MOS-N-FET-e	V-MOS, 1000V, 4A, 100W, <3,8Ω(2A)	18p	Fjd	BUZ357..358, 2SK1205, 2SK1359, 2SK1773
2SK2259	MOS-N-FET-e	V-MOS, LogL, 60V, 40A, 40W, <30mΩ(20A)	17c	Fjd	2SK1257, 2SK1653
2SK226	MOS-N-FET-e	=2SK225: 140V	20d	Hit	(2SK343..344)
2SK2260	MOS-N-FET-e	SMD, V-MOS, 220V, 1,2A, <4,5Ω(0,6A)	39b	Say	2SK1334
2SK2261	MOS-N-FET-e	V-MOS, 60V, 2A, 1,2W	78c	Rhm	2SK462, 2SK973, 2SK1763, 2SK1973
2SK2262	MOS-N-FET-e	V-MOS, LogL, 60V, 2A, 1,2W	78c	Rhm	2SK973, 2SK1763
2SK2263	MOS-N-FET-e	V-MOS, 500V, 5A, 60W	18c	Rhm	2SK1206, 2SK1523
2SK2264	MOS-N-FET-e*	V-MOS, 350V, 5A, 100W, <3Ω(3A)	18d	Hit	—
2SK2265	MOS-N-FET-e*	=2SK2264: 400V	18p	Hit	BUZ330..331, 2SK501
2SK2266	MOS-N-FET-e	V-MOS, LogL, 60V, 45A, 65W, <30mΩ(25A)	30p	Tos	2SK1919
2SK2267	MOS-N-FET-e	V-MOS, LogL, 60V, 60A, 150W, <11mΩ(30A)	77p	Tos	2SK1223, 2SK1259, 2SK1380
2SK2268	N-FET	=2SK2270: SMD	35d(2mm)	Say	—
2SK2269	N-FET	=2SK2270: SMD	35f(3mm)	Say	—
2SK227	MOS-N-FET-e	=2SK225: 160V	20d	Hit	(2SK344)
2SK2270	N-FET	15V, 30mA, 0,3W, Idss=1,2..12mA	40f	Say	—
2SK2273	MOS-N-FET-e	SMD, V-MOS, LogL, 12V, 0,5A, <0,48Ω	35a	Say	—
2SK2274	MOS-N-FET-e	V-MOS, 700V, 5A, 45W, <1,7Ω(2A)	17c	Tos	2SK1808
2SK2275	MOS-N-FET-e	V-MOS, 900V, ±3,5A, 35W, <2,8Ω(2A)	17c	Nec	2SK1356, 2SK1460
2SK2278(L,S)	MOS-N-FET-e	=2SK1317:	≈30p	Hit	—
2SK2279	MOS-N-FET-e	V-MOS, 60V, 2A, 10W, <0,35Ω, 20/80ns	30p	Shi	2SK973, 2SK1763, 2SK1973
2SK2260	MOS-N-FET-e	V-MOS, 60V, 5A, 10W, <0,18Ω, 50/130ns	30p	Shi	2SK1471, 2SK1719, 2SK1949
2SK2281	MOS-N-FET-e	V-MOS, 60V, 10A, 15W, <0,1Ω, 70/250ns	30p	Shi	2SK2414
2SK2262	MOS-N-FET-e	V-MOS, 60V, 10A, 30W, <0,1Ω, 70/250ns	30c	Shi	2SK1620
2SK2283	MOS-N-FET-e	=2SK2282: Iso, 20W	17c	Shi	BUK442-60, 2SK1033, 2SK1093, 2SK1344, ++
2SK2284	MOS-N-FET-e	V-MOS, 60V, 15A, 40W, <0,07Ω, 80/260ns	30c	Shi	2SK1648, 2SK1967
2SK2285	MOS-N-FET-e	=2SK2284: Iso, 25W	17c	Shi	2SK1094, 2SK1286, 2SK1419
2SK2286	MOS-N-FET-e	V-MOS, 60V, 20A, 50W, <45mΩ, 100/420ns	30c	Shi	2SK1622, 2SK1967
2SK2287	MOS-N-FET-e	=2SK2268: Iso, 30W	17c	Shi	2SK1095, 2SK1345..46, 2SK1420, 2SK1951 ++
2SK2268	MOS-N-FET-e	V-MOS, 60V, 30A, 60W, <30mΩ, 170/630ns	30c	Shi	2SK1792
2SK2269	MOS-N-FET-e	=2SK2288: Iso, 40W	17c	Shi	2SK1421, 2SK1653, 2SK1952
2SK2290	MOS-N-FET-e	V-MOS, 60V, 45A, 80W, <18mΩ, 240/960ns	30c	Shi	2SK1792, 2SK1919
2SK2291	MOS-N-FET-e	=2SK2290: Iso, 50W	17c	Shi	2SK1421, 2SK1653, 2SK1952
2SK2293	MOS-N-FET-e	V-MOS, 900V, 3A, 30W	17c	Ehm	2SK1356, 2SK1460
2SK2294	MOS-N-FET-e	V-MOS, 800V, 3A, 30W	17c	Ehm	2SK1356, 2SK1460
2SK2295	MOS-N-FET-e	V-MOS, 600V, 4A, 30W	17c	Ehm	2SK1118, 2SK2044
2SK2298	MOS-N-FET-e	V-MOS, 500V, 7A, 30W	17c	Rhm	2SK1352, 2SK1567, 2SK1609, 2SK1805, ++
2SK2299	MOS-N-FET-e	V-MOS, 450V, 7A, 30W	17c	Rhm	2SK1352, 2SK1566, 2SK1609, 2SK1805, ++
2SK23(A)-2..-9	N-FET	FM/VHF, 18..40V, Idss>2,7mA, Up<4,9V	10a	Son	2SK107, 2SK192
2SK2300	MOS-N-FET-e	V-MOS, LogL, 60V, 15A, 30W	17c	Rhm	2SK943, 2SK1286, 2SK1345
2SK2306(F5)	MOS-N-FET-e	V-MOS, LogL, 60V, 3A, 20W	30p	Rhm	2SK1113, 2SK1254, 2SK1262
2SK2307(F5)	MOS-N-FET-e	V-MOS, LogL, 100V, 2A, 20W	30p	Rhm	2SK1113, 2SK1299, 2SK1254, 2SK1284, ++
2SK2309	MOS-N-FET-e	V-MOS, LogL, 100V, 10A, 30W	17c	Hit	BUK545-100, 2SK1035, 2SK1305, 2SK1904++
2SK2311	MOS-N-FET-e	V-MOS, LogL, 60V, 25A, 40W, <46mΩ(12A)	30p	Tos	2SK1622
2SK2312	MOS-N-FET-e	V-MOS, LogL, 60V, 45A, 45W, <17mΩ(25A)	17c	Tos	2SK1257, 2SK1653, 2SK1952
2SK2313	MOS-N-FET-e	V-MOS, LogL, 60V, 60A, 150W, <11 mΩ(30A)	18p	Tos	BUK539-60, 2SK1256, 2SK1379
2SK2315	MOS-N-FET-e*	SMD, V-MOS, LogL, 60V, ±2A, <0,45Ω(1A)	39j	Hit	2SK1311, 2SK1470, 2SK1717, 2SK2055
2SK2316	MOS-N-FET-e	SMD, V-MOS, LogL, 20V, 2A, <0,2Ω(0,5A)	39b	Say	2SK1311, 2SK1470, 2SK1717, 2SK2315
2SK2317	MOS-N-FET-e	V-MOS, LogL, 20V, 4A, 20W, <85mΩ	30p	Say	2SK1112, 2SK1471, 2SK1719
2SK2318	MOS-N-FET-e	V-MOS, LogL, 20V, 12A, 30W, <38mΩ	30p	Say	2SK2414
2SK2319	MOS-N-FET-e	V-MOS, 800V, 7A, 90W, <1,7Ω(3,5A)	≈18c(p)	Tos	BUK638-800, 2SK1358, 2SK1502, 2SK1795++
2SK2320	MOS-N-FET-e	V-MOS, 800V, 8,5A, 90W, <1,2Ω(4A)	≈18c(p)	Tos	BUK638-800, 2SK1356, 2SK1502, 2SK1795
2SK2321	MOS-N-FET-e	V-MOS, 250V, 12A, 70W, <0,35Ω(5A)	30p	Say	2SK1638, 2SK2063
2SK2322(L,S)	MOS-N-FET-e*	V-MOS, LogL, 60V, 15A, 50W, <50mΩ(8A)	30p	Hit	2SK1648
2SK2328	MOS-N-FET-e	=2SK1403A: 7A, 75W	17c	Hit	—
2SK2329(L,S)	MOS-N-FET-e	V-MOS, LogL, 30V, 10A, 20W, <40mΩ(5A)	79p	Hit	2SK2414
2SK2330	MOS-N-FET-e*	=2SK1168:	≈30p	Hit	—
2SK2331	GaAs-N-FET-d	SHF, 3V, Idss=25..120mA, Up<2V, 12GHz	52(GSDS)	Tos	—

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2SK2332	GaAs-N-FET-d	SHF, 3V, Idss=20..80mA, Up<2V, 12GHz	52(GSDS)	Tos	—
2SK2333	MOS-N-FET-e	V-MOS, 700V, 6A, 50W, <2Ω, 70/160ns	17c	Shi	—
2SK2334(L,S)	MOS-N-FET-e*	V-MOS, LogL, 60V, 20A, 30W, <55mΩ(10A)	30p	Hit	—
2SK2341	MOS-N-FET-e	V-MOS, 250V, ±11A, 35W, <0,26Ω(6A)	17c	Nec	2SK1036, 2SK1762, 2SK2011
2SK2343	MOS-N-FET-e	SMD, V-MOS, LogL, 20V, 6A, 2W, <60mΩ	6-MDIP	Say	—
2SK2344	MOS-N-FET-e	V-MOS, 20V, 7A, 2W, <35mΩ(7A)	6-MDIP	Say	—
2SK2345	MOS-N-FET-e*	V-MOS, 350V, 6A, 35W, <0,8Ω(5A)	17c	Hit	BUK445-400, 2SK1351, 2SK1608, 2SK1627++
2SK2346	MOS-N-FET-e*	V-MOS, LogL, 60V, 20A, 25W, <50mΩ(10A)	17c	Hit	2SK1095, 2SK1214, 2SK1345, 2SK1697
2SK2347	MOS-N-FET-e	V-MOS, 1000V, 20A, 160W, <0,6Ω(10A)	≈77	Say	—
2SK2348	MOS-N-FET-e	V-MOS, 1200V, 14A, 160W, <1,5Ω(7A)	≈77	Say	—
2SK2349	MOS-N-FET-e	V-MOS, 1500V, 10A, 160W, <2,5Ω(5A)	≈77	Say	—
2SK2350	MOS-N-FET-e	V-MOS, 200V, 6,5A, 30W, <0,4Ω(5A)	17c	Tos	BUK545-200, 2SK1568..69, 2SK1668
2SK2351	MOS-N-FET-e	V-MOS, SMPS, 600V, 6A, 100W, <1,25Ω	17p	Tos	BUZ91, 2SK1117, 2SK1924
2SK2352	MOS-N-FET-e	=2SK2351: Iso	17c	Tos	2SK1118, 2SK1404, 2SK2045
2SK2353	MOS-N-FET-e	=2SK2355: Iso, ±4,5A, 30W	17c	Nec	2SK1231..32, 2SK1351, 2SK1608
2SK2354	MOS-N-FET-e	=2SK2356: Iso, ±4,5A, 30W	17c	Nec	2SK1232, 2SK1351, 2SK1608
2SK2355	MOS-N-FET-e	V-MOS, 450V, ±5A, 50W, <1,4Ω(2,5A)	17p	Nec	2SK1156, 2SK1246, 2SK1440, 2SK1751
2SK2355	MOS-N-FET-e	=2SK2355: 500V, <1,5Ω(2,5A)	17p	Nec	2SK1156, 2SK1246, 2SK1751
2SK2355..2356Z	MOS-N-FET-e	=2SK2355: 2356	30p		2SK1540..1541
2SK2357	MOS-N-FET-e	=2SK2359: Iso, ±6A, 35W	17c	Nec	2SK1352, 2SK1566..67, 2SK1609, 2SK1605++
2SK2358	MOS-N-FET-e	=2SK2360: Iso, ±6A, 35W	17c	Nec	2SK1352, 2SK1567, 2SK1609, 2SK1605,++
2SK2359	MOS-N-FET-e	V-MOS, 450V, ±7A, 75W, <0,9Ω(4A)	17p	Nec	2SK1495..96, 2SK1574, (IRF840, IRF842)
2SK2359..2360Z	MOS-N-FET-e	=2SK2359: 2360	30p		2SK1315..16, 2SK1540..1541
2SK2360	MOS-N-FET-e	=2SK2359: 500V, 1Ω(4A)	17p	Nec	2SK1496, 2SK1574, (IRF840, IRF842)
2SK2361	MOS-N-FET-e	=2SK2365: 100W	18p	Nec	2SK644, 2SK724, 2SK1488, 2SK1784..85,++
2SK2362	MOS-N-FET-e	=2SK2366: 100W	16p	Nec	2SK644, 2SK724, 2SK1488, 2SK1765,++
2SK2363	MOS-N-FET-e	=2SK2365: Iso, 35W	17p	Nec	—
2SK2364	MOS-N-FET-e	=2SK2366: Iso, 35W	17p	Nec	—
2SK2365	MOS-N-FET-e	V-MOS, 450V, ±10A, 75W, <0,5Ω(5A)	17p	Nec	2SK1442, 2SK1503
2SK2365..2366Z	MOS-N-FET-e	=2SK2365: 2366	30p		—
2SK2366	MOS-N-FET-e	=2SK2365: 500V, <0,6Ω(5A)	17p	Nec	2SK1503
2SK2367	MOS-N-FET-e	V-MOS, 450V, ±15A, 120W, <0,5Ω(8A)	18p	Nec	2SK725, 2SK768, 2SK899, 2SK1610, 2SK1745
2SK2366	MOS-N-FET-e	V-MOS, 500V, ±15A, 120W, <0,6Ω(6A)	18p	Nec	2SK725, 2SK766, 2SK899, 2SK1610, 2SK1745
2SK2369	MOS-N-FET-e	V-MOS, 450V, ±20A, 120W, <0,35Ω(10A)	16p	Nec	2SK870, 2SK1409, 2SK1411, 2SK1497..1500+
2SK2370	MOS-N-FET-e	V-MOS, 500V, ±20A, 120W, <0,4Ω(10A)	16p	Nec	2SK870, 2SK1409, 2SK1411, 2SK1498/1500++
2SK2371	MOS-N-FET-e	V-MOS, 450V, ±25A, 160W, <0,25Ω(13A)	16p	Nec	2SK1499..1500
2SK2372	MOS-N-FET-e	V-MOS, 500V, ±25A, 160W, <0,27Ω(13A)	18p	Nec	2SK1500
2SK2373	MOS-N-FET-e*	SMD, V-MOS, LogL, 30V, 0,2A, <1,4Ω(10mA)	35a	Hit	(2SK1590..91)
2SK2373	MOS-N-FET-e*	integr. Rgate			—
2SK2376	MOS-N-FET-e	V-MDS, LogL, 60V, 45A, 100W, <17mΩ(25A)	30p	Tos	2SK1792
2SK2376	MOS-N-FET-e	V-MDS, 200V, 13A, 30W, <0,21Ω(7A)	17c	Say	2SK1350
2SK2379	MOS-N-FET-e	V-MOS, 200V, 20A, 30W, <95mΩ(10A)	17c	Say	—
2SK238	N-FET	SMD, FM, 20V, Idss>0,5mA, Up<2,5V	35e	Nec	BF510
2SK2361	MOS-N-FET-e	V-MOS, 200V, 5A, 25W, <0,8Ω(2,5A)	17c	Tos	BUK444-200, BUZ73, 2SK2010
2SK2382	MOS-N-FET-e	V-MOS, 200V, 15A, 45W, <0,16Ω(10A)	17c	Tos	2SK1350, 2SK2012
2SK2390	MOS-N-FET-e*	V-MOS, LogL, 60V, 12A, 20W, <90mΩ(6A)	17c	Say	2SK1093, 2SK1256, 2SK1305..06, 2SK1344++
2SK2393	MOS-N-FET-e*	V-MOS, 1500V, 6A, 200W, <2,8Ω(4A)	47c	Hit	—
2SK2394	N-FET	=2SK2395: SMD	35f	Say	BF513
2SK2395	N-FET	HF, 15V, Idss=6..32mA, Up<1,6V	40a	Say	BC264C..D
2SK24	N-FET	NF/AM, 40V, Idss=0,6..24mA, Up<6V	≈2a	Say	BFS71, 2N3622, 2N5457, 2SK246, 2SK330++
2SK240	N-FET	Dual, 40V, Idss>2,6mA, Up<1,5V	7e+7a	Tos	—
2SK2403	MOS-N-FET-e	FREDFET, 450V, 3A, 50W, <3,2Ω(1,5A)	30p	Say	—
2SK2404	MOS-N-FET-e	FREDFET, 450V, 5A, 60W, <1,6Ω(3A)	30p	Say	—
2SK2405	MOS-N-FET-e	FREDFET, 450V, 10A, 70W, <0,75Ω(6A)	30p	Say	—
2SK2406	MOS-N-FET-e	FREDFET, 450V, 1A, 30W, <4,5Ω(5A)	30p	Say	—
2SK2407	MOS-N-FET-e	FREDFET, 450V, 10A, 70W, <0,75Ω(6A)	17p	Say	—
2SK2408	MOS-N-FET-e*	V-MOS, 500V, 7A, 60W, <0,9Ω(4A)	17c	Hit	2SK1496, 2SK1574, (IRF840, IRF842)
2SK241	MOS-N-FET-d*	FM/VHF, 20V, Idss>1,5mA, Up<2,5V	41d	Tos	—
2SK2411	MOS-N-FET-e*	V-MOS, LogL, 60V, ±30A, 75W, <40mΩ(15A)	17p	Nec	2SK1296
2SK2411Z	MOS-N-FET-e*	=2SK2411:	30p		2SK1900
2SK2414(Z)	MOS-N-FET-e*	V-MOS, LogL, 60V, ±10A, 20W, <0,07Ω(5A	30p	Nec	—
2SK2415(Z)	MOS-N-FET-e*	V-MOS, LogL, 60V, ±6A, 20W, <0,1Ω(4A)	30p	Nec	2SK1472, 2SK1475, 2SK1746
2SK2416(L,S)	MOS-N-FET-e*	V-MOS, LogL, 50V, 7A, 20W, <0,05Ω(4A)	30p	Hit	2SK1472, 2SK1475, 2SK1748
2SK242	N-FET	SMD, FM/VHF, 20V, Idss>0,6mA, Up<2,5V	35e	Say	BF510, 2SK238
2SK2422	MOS-N-FET-e*	V-MOS, 650V, 4A, 20W, <2,6Ω(2A)	15c	Hit	2SK1118, 2SK1404, 2SK1637
2SK2423	MOS-N-FET-e*	V-MOS, 450V, 7A, 35W, <0,7Ω(4A)	15c	Hit	2SK1352, 2SK1566..67, 2SK1609, 2SK1605++

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2SK2424	MOS-N-FET-e*	V-MOS, 450V, 8A, 35W, <0,55Ω(4A)	17c	Hit	2SK1352, 2SK1566..67, 2SK1609, 2SK1805++
2SK2425	MOS-N-FET-e*	V-MOS, 250V, 7A, 30W, <0,55Ω(4A)	15c	Hit	2SK1478, 2SK1568..69, 2SK1668
2SK2426	MOS-N-FET-e*	V-MOS, 250V, 12A, 35W, <0,35Ω(6A)	15c	Hit	2SK1036, 2SK1762
2SK2431	MOS-N-FET-e*	V-MOS, 450V, 3A, 25W, <2,8Ω(3A)	15c	Hit	BUK445-450, 2SK1572, 2SK1767
2SK2432	MOS-N-FET-e	V-MOS, LogL, 30V, 35A, 50W, <25mΩ		Say	—
2SK2433	MOS-N-FET-e	V-MOS, LogL, 60V, 25A, 50W, <40mΩ		Say	—
2SK2434	MOS-N-FET-e	V-MOS, 450V, 5A, 40W, <1,4Ω		Say	—
2SK2435	MOS-N-FET-e	V-MOS, 800V, 3,5A, 40W, <3,6Ω		Say	—
2SK2436	MOS-N-FET-e	V-MOS, 800V, 7A, 50W, <1,8Ω		Say	—
2SK2437	MOS-N-FET-e	SMD, V-MOS, 30V, 2A, <0,18Ω	39b	Say	2SK1311, 2SK1717, 2SK1763
2SK2438	MOS-N-FET-e	V-MOS, 30V, 4A, 20W, <80mΩ	30p	Say	2SK1112, 2SK1471, 2SK1719
2SK2438	MOS-N-FET-e	V-MOS, 30V, 12A, 30W, <40mΩ	30p	Say	2SK2414
2SK2440	MOS-N-FET-e	V-MOS, LogL, 20V, 6A, 2W, <36mΩ(2A)	8-MDIP	Say	—
2SK2441	MOS-N-FET-e	V-MOS, LogL, 20V, 7A, 2W, <32mΩ(7A)	8-MDIP	Say	—
2SK2442	MOS-N-FET-e	V-MOS, LogL, 30V, 7A, 2W, <48mΩ(4Ω)	8-MDIP	Say	—
2SK246	N-FET	Uni, 50V, Idss>1,2mA, Up<6V	7e	Tos	2N5457, 2SK330
2SK2464	MOS-N-FET-e	V-MOS, 30V, 50A, 50W, <12mΩ		Say	—
2SK247	N-FET	SMD, HF, 15V, Idss>0,5mA, Up<3V	35f	Mat	—
2SK25	N-FET	AM/FM, 18V, Idss=0,624mA, Up<7,2V	≈2a	Say	BF244..245, BFS71, 2N3822..23,++
2SK2529	MOS-N-FET-e*	V-MOS, LogL, 60V, 50A, 35W, <0,01Ω(25A)	15c	Tos	2SK1653
2SK2530	MOS-N-FET-e	FREDFET, 250V, 2A, 20W, <2Ω(1A)	30p	Say	—
2SK2531	MOS-N-FET-e	FREDFET, 250V, 6A, 30W, <0,8Ω		Say	—
2SK2532	MOS-N-FET-e	FREDFET, 250V, 10A, 40W, <0,4Ω		Say	—
2SK2533	MOS-N-FET-e	FREDFET, 250V, 12A, 45W, <0,28Ω		Say	—
2SK2534	MOS-N-FET-e	FREDFET, 250V, 16A, 50W, <0,2Ω		Say	—
2SK2539	N-FET	SMD, 15V, Idss=10..50mA	35f	Say	—
2SK2542	MOS-N-FET-e	V-MOS, 500V, 6A, 100W, <0,85Ω(4A)	17p	Tos	IRF840, 2SK1496, 2SK1574
2SK2543	MOS-N-FET-e	=2SK2542: Iso, 40W	17c	Tos	2SK1232, 2SK1351, 2SK1608
2SK2544	MOS-N-FET-e	V-MOS, 800V, 6A, 100W, <1,25Ω(3A)	17p	Tos	BUZ91, 2SK1117, 2SK1924
2SK2545	MOS-N-FET-e	=2SK2544: Iso, 40W	17c	Tos	2SK1118, 2SK1637, 2SK2097, 2SK2045, ++
2SK2552	N-FET	SMD, Kondens.-Mikrofon, 20V, Idss>40μA	35b(1,6mm)	Nec	—
2SK2553(L,S)	MOS-N-FET-e*	=2SK2529:	79p	Hit	—
2SK2554	MOS-N-FET-e*	V-MOS, LogL, 60V, 75A, 150W, <6mΩ(40A)	18p	Hit	—
2SK2555	MOS-N-FET-e	V-MOS, 30V, 12A, 30W, <46mΩ	30p	Say	2SK2414
2SK2556	MOS-N-FET-e	V-MOS, 30V, 6A, 2W, <46mΩ	8-MDIP	Say	—
2SK2557	MOS-N-FET-e	V-MOS, 30V, 7A, 2W, <37mΩ	8-MDIP	Say	—
2SK2568	MOS-N-FET-e*	V-MOS, S-L, 500V, 12A, 100W, <0,6Ω(6A)	18p	Hit	2SK724, 2SK1488, 2SK1723, 2SK1785, ++
2SK2569	MOS-N-FET-e*	SMD, V-MOS, LogL, 50V, 0,2A, <2,6Ω(0,1A)	35a	Hit	—
2SK2569	MOS-N-FET-e*	integr. Rgate			—
2SK2570	MOS-N-FET-e*	SMD, V-MOS, LogL, 20V, 0,2A, <1,1Ω	35a	Hit	—
2SK2570	MOS-N-FET-e*	integr. Rgate			—
2SK256	MOS-N-FET-e	V-MOS, 250V, 8A, 125W, <1,3Ω, 25/140ns	23e	Hit	(2SK277..278, 2SK293, 2SK299)
2SK2562	MOS-N-FET-e*	V-MOS, 350V, 13A, 75W, <0,4Ω(7A)	17p	Hit	—
2SK2568	MOS-N-FET-e*	V-MOS, LogL, 60V, 60A, 125W, <10mΩ(30A)	18p	Hit	BUK539-60, 2SK1258, 2SK1379, 2SK2121
2SK259	MOS-N-FET-e	V-MOS, 350V, 5A, 125W, <3Ω, 25/140ns	23e	Hit	(BUZ44, BUZ46, BUZ63)
2SK2590	MOS-N-FET-e*	V-MOS, 200V, 7A, 50W, <0,45Ω(4A)	17p	Hit	BUZ30..32, BUZ73, 2SK741, 2SK1319
2SK2591	MOS-N-FET-e*	V-MOS, S-L, 500V, 6A, 35W, <0,6Ω(4A)	17c	Hit	2SK1532, 2SK1567, 2SK1805, 2SK2117, ++
2SK2592	MOS-N-FET-e	FREDFET, 250V, 13A, 60W, <0,27Ω	30p	Say	—
2SK260	MOS-N-FET-e	V-MOS, 400V, 5A, 125W, <3Ω, 25/140ns	23e	Hit	(BUZ44, BUZ46, BUZ63)
2SK2602	MOS-N-FET-e	V-MOS, SMPS, 800V, 6A, 125W, <1,25Ω(3A)	18p	Tos	2SK1032, 2SK1358, 2SK1502, 2SK1614,++
2SK2604	MOS-N-FET-e	V-MOS, SMPS, 800V, 5A, 125W, <2,2Ω(3A)	18p	Tos	2SK793..94, 2SK727, 2SK1213, 2SK1403,++
2SK2605	MOS-N-FET-e	V-MOS, 900V, 3A, 100W, <4,3Ω(1,5A)	17p	Tos	BUK456-1000
2SK2608	MOS-N-FET-e	V-MOS, 900V, 3A, 100W, <4,3Ω(1,5A)	17p	Tos	BUK456-000
2SK261	N-FET	≈2SK213		Hit	→2SK213
2SK2610	MOS-N-FET-e	V-MOS, SMPS, 900V, 5A, 125W, <2,5Ω	18p	Tos	2SK727, 2SK1341, 2SK1649..50, 2SK1794,++
2SK2611	MOS-N-FET-e	V-MOS, 900V, 9A, 150W, <1,4Ω(4A)	18p	Tos	2SK1796, 2SK1933
2SK2616	MOS-N-FET-e	V-MOS, 500V, 2A, 30W, <4Ω	30p	Say	—
2SK2617	MOS-N-FET-e	V-MOS, 500V, 4A, 25W, <1,6Ω	17c	Say	2SK1351, 2SK1232, 2SK1608, 2SK1627,++
2SK2618(LS)	MOS-N-FET-e	V-MOS, 500V, 5A, 30W, <1,25Ω	17c	Say	2SK1351, 2SK1232, 2SK1808, 2SK1627,++
2SK2619	MOS-N-FET-e	V-MOS, 500V, 6A, 70W, <1,25Ω	30p	Say	2SK1540..1541
2SK262	N-FET	≈2SK213		Hit	→2SK213
2SK2620	MOS-N-FET-e	V-MOS, 500V, 7A, 35W, <0,8Ω	17c	Say	2SK1352, 2SK1567, 2SK1805, 2SK2117
2SK2621	MOS-N-FET-e	V-MOS, 500V, 12A, 120W, <0,6Ω	18p	Say	2SK644, 2SK724, 2SK1468, 2SK1723, ++
2SK2622	MOS-N-FET-e	V-MOS, 500V, 14A, 125W, <0,52Ω	18p	Say	2SK725, 2SK788, 2SK899, 2SK1610, 2SK1745
2SK2623	MOS-N-FET-e	V-MOS, 600V, 1,5A, 30W, <5,5Ω	30p	Say	2SK1533, 2SK1880
2SK2624(LS)	MOS-N-FET-e	V-MOS, 800V, 3A, 25W, <2,6Ω	17c	Say	2SK1572, 2SK1767

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2SK2625(LS)	MOS-N-FET-e	V-MOS, 600V, 4A, 30W, <2Ω	17c	Say	2SK1118, 2SK1404, 2SK1637
2SK2626	MOS-N-FET-e	V-MOS, 600V, 5A, 70W, <2Ω	30p	Say	—
2SK2627	MOS-N-FET-e	V-MOS, 600V, 5A, 40W, <2Ω		Say	—
2SK2628(LS)	MOS-N-FET-e	V-MOS, 600V, 6A, 35W, <1,2Ω	17c	Say	2SK1118, 2SK1404, 2SK2045
2SK2629	MOS-N-FET-e	V-MOS, 600V, 10A, 120W, <1Ω	18p	Say	BUZ334, 2SK1723
2SK263	N-FET	=2SK213		Hit	→2SK213
2SK2630	MOS-N-FET-e	V-MOS, 600V, 10A, 120W, <1Ω	18p	Say	BUZ334, 2SK1723
2SK2631	MOS-N-FET-e	V-MOS, 800, 1A, 30W, <10Ω	30p	Say	2SK1533
2SK2632(LS)	MOS-N-FET-e	V-MOS, 600V, 2,5A, 25W, <4,8Ω	17c	Say	BUK445-600, 2SK1142, 2SK1834
2SK2633(LS)	MOS-N-FET-e	V-MOS, 600V, 3A, 30W, <3,6Ω	17c	Say	2SK1356, 2SK1460
2SK2634	MOS-N-FET-e	V-MOS, 800V, 3,5A, 70W, <3,6Ω	30p	Say	2SK1510, 2SK1659
2SK2635	MOS-N-FET-e	V-MOS, 800V, 5A, 100W, <2,6Ω	18p	Say	2SK727, 2SK1341, 2SK1849..50, 2SK1794, ++
2SK2636	MOS-N-FET-e	V-MOS, 600V, 7A, 120W, <1,6Ω	18p	Say	2SK1356, 2SK1814, 2SK1502, 2SK1692, ++-
2SK2637	MOS-N-FET-e	V-MOS, 20V, 8A, 2W, <25mΩ	8-MDIP	Say	—
2SK264	N-FET	=2SK214		Hit	→2SK214
2SK266	N-FET	NF-V, 15V, Zin>200MΩ		Tos	—
2SK2662	MOS-N-FET-e	V-MOS, 500V, 5A, 35W, <1,5Ω(2,5A)	17c	Tos	BUK445-500, 2SK1232, 2SK1351, 2SK1627++
2SK2684(L,S)	MOS-N-FET-e*	V-MOS, LogL, 30V, 30A, 50W, <28mΩ(15A)	30p	Hit	2SK1900, 2SK2411Z
2SK2698	MOS-N-FET-e	V-MOS, SMPS, 500V, 15A, 150W, <0,4Ω(7A)	18p	Tos	2SK560, 2SK725, 2SK1610, 2SK1745, ++
2SK270	N-FET	Dual, 40V, Idss>1mA, Up<2V	7-SIP	Tos	—
2SK271	MOS-N-FET-e	V-MOS-L, 140V, 8A, 120W	23a	Tos	2SK405, 2SK831, 2SK633
2SK272	MOS-N-FET-e	=2SK271: 7A, 100W	18p	Tos	2SK405, 2SK413..414, 2SK631, 2SK633
2SK2725	MOS-N-FET-e*	V-MOS, 500V, 6A, 30W, <1,6Ω(3A)	17c	Hit	2SK1351, 2SK1608, 2SK1993, 2SK2115, ++
2SK2726	MOS-N-FET-e*	V-MOS, 500V, 7A, 30W, <0,95Ω(4A)	17c	Hit	2SK1352, 2SK1609, 2SK1805, 2SK2117, ++
2SK2727	MOS-N-FET-e*	V-MOS, 500V, 10A, 125W, <0,95Ω(5A)	18p	Hit	2SK644, 2SK724, 2SK1498, 2SK1785, ++
2SK2726	MOS-N-FET-e*	V-MOS, 500V, 18A, 150W, <0,45Ω(9A)	18p	Hit	2SK1170, 2SK1411, 2SK1500, 2SK1680, ++
2SK2729	MOS-N-FET-e*	V-MOS, 500V, 20A, 150W, <0,29Ω(10A)	18p	Hit	2SK1170, 2SK1411, 2SK1500, 2SK1680, ++
2SK273	GaAs-N-FET	UHF, S..X-Band, 8V, 100mA, 12GHz	52(SGSD)	Mit	—
2SK2730	MOS-N-FET-e*	V-MOS, 500V, 25A, 175W, <0,24Ω(15A)	18p	Hit	2SK1500
2SK2734	MOS-N-FET-e*	V-MOS, LogL, 30V, 5A, 0,9W, <0,55mΩ	7c(9mm)	Hit	—
2SK2735	MOS-N-FET-e*	V-MOS, LogL, 30V, 20A, 20W, <28mΩ(10A)	30p	Hit	2SK2334
2SK2736	MOS-N-FET-e*	V-MOS, LogL, 30V, 30A, 25W, <85mΩ(15A)	17c	Hit	2SK1262
2SK2737	MOS-N-FET-e*	V-MOS, LogL, 30V, 45A, 30W, <14mΩ(20A)	17c	Hit	2SK1257, 2SK1653, 2SK1952, 2SA2120
2SK2738	MOS-N-FET-e*	V-MOS, LogL, 60V, 40A, 35W, <20mΩ(20A)	17c	Hit	2SK1257, 2SK1653, 2SK1952, 2SA2120
2SK274	GaAs-N-FET	UHF, S..K-Band, 8V, 100mA, 12GHz	52(SGSD)	Mit	—
2SK275	GaAs-N-FET	UHF, S..X-Band, 8V, 100mA, 4GHz	52(SGSD)	Mit	—
2SK276	GaAs-N-FET	UHF, S..X-Band, 8V, 80mA, 18GHz	52(SGSD)	Mit	—
2SK277	MOS-N-FET-e	V-MOS-L, 350V, 7A, 100W, <1,5Ω, 40/60ns	23a	Nec	BUZ330..331, 2SK298, 2SK501
2SK278	MOS-N-FET-e	=2SK277: 400V	23a	Nec	BUZ330..331, 2SK298, 2SK501
2SK2788	MOS-N-FET-e*	SMD, V-MOS, LogL, 60V, 2A, <0,18Ω(1A)	39b	Hit	2SK1273, 2SK1470, 2SK1717, 2SK2315, ++
2SK279	GaAs-N-FET	UHF, S..X-Band, 5V, 250mA, 8GHz	52(SGSD)	Mit	—
2SK2798	MOS-N-FET-e*	V-MOS, LogL, 60V, 5A, 20W, <0,16Ω(3A)	30p	Hit	2SK1112, 2SK1471, 2SK1719, 2SK1949, ++
2SK280	GaAs-N-FET	UHF, X..Ku-Band, 5V, 100mA, 15GHz	52(SGSD)	Nec	—
2SK2600	MOS-N-FET-e	V-MOS, S-L, 60V, 40A, 50W, <20mΩ(20A)	17p	Hit	2SK1418, 2SK1542, 2SK1911
2SK2601	MOS-N-FET-e	V-MOS, LogL, 60V, 50A, 100W, <10mΩ(25A)	17p	Hit	BUK556-20
2SK2802	MOS-N-FET-e*	SMD, V-MOS, LogL, 30V, 0,5A, <0,28Ω	35a	Hit	—
2SK2802	MOS-N-FET-e*	integr. Rgate			—
2SK281	GaAs-N-FET	VHF, C-Band, 5V, 120mA, 6GHz	52(SGSD)	Nec	—
2SK283	N-FET	SMD, NF-Tr, 60V, Idss>1,2mA, Up=0,75V	35f	Say	—
2SK286	MOS-N-FET-e	V-MOS, 60V, 8A, 100W, <0,8Ω, 80/110ns	20d	Hit	2SK225..227, (2SK343..344)
2SK2S7	MOS-N-FET-e	V-MOS, 60V, 8A, 100W, <0,6Ω, 25/350ns	20d	Hit	2SK225..227, (2SK343..344)
2SK286	MOS-N-FET-e	=2SK287: 80V	20d	Hit	2SK225..227, (2SK343..344)
2SK289	MOS-N-FET-e	V-MOS, 60V, 8A, 100W, 25/350ns	23a	Hit	2SK175..176, (BUZ33)
2SK290	MOS-N-FET-e	=2SK289: 100V	23a	Hit	2SK175..178, (BUZ33)
2SK281	N-FET	Video-Camera, 15V, Idss>5mA, Up<3V	7d	Hit	—
2SK292	N-FET	FM-V/M/O, 20V, Idss>0,5mA, Up<2,5V	40f	Nec	BF410A, 2SK193, 2SK195, 2SK212
2SK293(A)	MOS-N-FET-e	V-MOS, S-L, 300V, 7A, 100W, <1,3Ω	23a	Nec	2SK277 278, 2SK298, 2SK501
2SK2S4	MOS-N-FET-e	V-MOS, 60V, 5A, 30W, 0,4Ω, 40/70ns	17p	Hit	IRF510..513, 2SK357..356, 2SK917, ++
2SK295	MOS-N-FET-e	=2SK294: 100V	17p	Hit	IRF510, IRF512, 2SK357..356, 2SK917, ++
2SK296	MOS-N-FET-e	V-MOS, 300V, 1A, 30W, 2,5<4Ω, 20/70ns	17p	Hit	IRF712
2SK296	MOS-N-FET-e	V-MOS, 400V, 8A, 100W, <1,75Ω, 50/120ns	23a	Hit	BUZ54, BUZ94, 2SK512, 2SK724
2SK299	MOS-N-FET-e	=2SK298: 450V	23a	Hit	BUZ54, BUZ94, 2SK512, 2SK724
2SK30(A,ATM)	N-FET	NF/Uni, ra, 50V, Idss>0,3mA, Up<5V	7e	Tos, Mic	BFS70, 2N3821, 2SK40, 2SK46, 2SK59, ++
2SK300	N-FET	SMD, VHF, 15V, Idss>9,5mA, Up<2V	35f	Son	(BF513)
2SK301	N-FET	Uni, ra, 55V, 30mA, Idss>0,5mA, Up<5V	7a	Mat	BFS70, 2N3821, 2N4220, 2SK104, ++
2SK302	MOS-N-FET-d	SMD, VHF, 20V, Idss>1,5mA, Up<2,5V	35c	Tos	—

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2SK303	N-FET	=2SK304: SMD	35f	Say	2SK160
2SK304	N-FET	Analog-S, 30V, Idss>0,6mA, Up<4V	40e	Say	BFS70, 2N3821, 2N4220, 2SK104, 2SK301 ++
2SK308	MOS-N-FET-e	V-MOS, 120V, 10A, 100W, <0,3Ω, 60/160ns	23a	Hit	BUZ35, 2SK401, 2SK631, 2SK633
2SK310	MOS-N-FET-e	V-MOS, 400V, 3A, 40W, <4Ω, 25/70ns	17p	Hit	BUZ60, BUZ76, IRF720, IRF722, 2SK1244+
2SK311	MOS-N-FET-e	=2SK310: 450V	17p	Hit	BUZ41A..42, 2SK1244, 2SK1493..1494,++
2SK312	MOS-N-FET-e	V-MOS, 400V, 12A, 125W, <0,9Ω, 70/200ns	23a	Hit	BUZ45, BUZ64, 2SK512, 2SK724
2SK313	MOS-N-FET-e	=2SK312: 460V	23a	Hit	BUZ45, 2SK512, 2SK724
2SK314	N-FET	Uni, ra, 40V, 50mA, Idss>5mA, Up<3V	2b	Nec	BC264, BF410C, 2SK147, 2SK168
2SK315	N-FET	FM-VM/O, 20V, Idss>2,5mA, Up<3,5V	40d	Say	BF410B, 2SK192
2SK316	N-FET	SMD, Video-Camera, 10V, Idss>5mA, Up<3V	35f	Mat	2SK321
2SK317	MOS-N-FET-e*	V-MOS, VHF-L, 180V, 8A, PQ>120W(100MHz)	57(SGSD)	Hit	—
2SK318	MOS-N-FET-e*	V-MDS, VHF-L, 160V, 4A, PQ>90W(100MHz)	57(SGSD)	Hit	—
2SK319	MOS-N-FET-e	V-MOS, 400V, 5A, 50W, <1,83Ω, 50/120ns	17p	Hit	BUZ41A..42, BUZ60, 2SK893, 2SK1246,++
2SK32	N-FET	Uni, 35V, 20mA, Idss<10mA, Up<4V	7e	Nec	BFS70, 2N3821, 2SK40, 2SK46, 2SK59, ++
2SK320	MOS-N-FET-e	=2SK319: 450V	17p	Hit	BUZ41A..42, 2SK552, 2SK893, 2SK1246,++
2SK321	N-FET	SMD, Video-Camera, 15V, Idss>5mA, Up<3V	35f	Mat	—
2SK322	N-FET	SMD, HF, 15V, 50mA, Idss>5mA, Up<3V	35f	Hit	—
2SK323	N-FET	SMD, Uni, 40V, Idss>1,6mA, Up<1,5V	35f	Hit	—
2SK324	MOS-N-FET-e	V-MOS, S-L, 400V, 10A, 120W, <0,6Ω	23a	Tos	BUZ45, BUZ64, 2SK312..313
2SK325	MOS-N-FET-e	=2SK324: 450V, <0,7Ω	23a	Tos	BUZ45, BUZ339, 2SK313, 2SK724
2SK33	N-FET	FM/VHF, 20V, Idss=2,5..20mA, Up<8V	7d	Mit,Mic	BF244..245, BFS71, 2N3822..23,++
2SK330	N-FET	Uni, 50V, Idss>1,2mA, Up<0,8V	41e	Tos	2N5457, 2SK248
2SK331	N-FET	NF-V, 20V, Idss=0,06..0,8mA		Say	—
2SK332	N-FET	Dual, 40V, 20mA, Idss>1,2mA, Up=0,5V		Say	—
2SK333	N-FET	Dual, 60V, 20mA, Idss>1,2mA, Up<3V		Say	—
2SK334	N-FET	=2SK331: SMD	≈35f	Say	—
2SK336	MOS-N-FET-e	Uni, 50V, 0,4A, 0,6W, 12Ω	7d	Say	—
2SK337	MOS-N-FET-a	V-MOS-L, 500V, ±0,1A, 10W, <100Ω(20mA)	14j	Nec	—
2SK338	MOS-N-FET-a	V-MOS, S-L, 400V, ±5A, 40W, <1,5Ω(2A)	17c	Nec	BUZ41A..42, BUZ60, 2SK552, 2SK1246,++
2SK339	MOS-N-FET-a	V-MOS, S-L, 100V, ±5A, 40W, <0,5Ω(3A)	17c	Nec	BUZ30, BUZ73, IRF510, IRF512, 2SK917
2SK34	N-FET	NF/Uni, 30V, Idss>0,3mA, Up<6V	7e	Mit,Mic	BFS70, 2N3389, 2N3821, 2SK381, ++
2SK343	MOS-N-FET-e	V-MDS, 140V, 8A, 100W, <0,5Ω, 100/90ns	20p	Hit	(2SK226..227)
2SK344	MOS-N-FET-e	=2SK343: 160V	20p	Hit	(2SK227)
2SK345	MOS-N-FET-e	V-MOS, 40V, 5A, 30W, <0,4Ω, 40/70ns	17p	Hit	IRF510..513, 2SK357, 2SK463, 2SK917,++
2SK346	MOS-N-FET-e	=2SK345: 60V	17p	Hit	IRF510..513, 2SK357, 2SK463, 2SK917,++
2SK347(L,S)	MOS-N-FET-e	V-MOS, 400V, 1A, 10W	30p	Hit	2SK535, 2SK579 580, 2SK945, 2SK1151 ,++
2SK349	MOS-N-FET-e	V-MOS, 400V, 10A, 100W, <0,9Ω, 70/200ns	18p	Hit	BUZ326, BUZ351, 2SK1752, 2SK1765,++
2SK35	N-FET	Uni, 20V, 20mA, Idss<16mA, Up<1,6V	10e	Son	2N5247, 2SK186..187, 2SK363..364,++
2SK350	MOS-N-FET-e	=2SK349: 450V	18p	Hit	BUZ339, 2SK896, 2SK1752, 2SK1785,++
2SK351	MOS-N-FET-e	V-MOS, 800V, 5A, 125W, <3Ω, 100/300ns	23a	Hit	BUZ54, BUZ64, 2SK793, 2SK1213
2SK352	MOS-N-FET-e	V-MOS, 250V, 0,3A, 8W, 30Ω	14b(j)	Hit	BST78, 2SK511
2SK353	GaAs-N-FET	UHF, C..Ku-Band, 5V, 120mA, 15GHz	52(SGSD)	Nec	—
2SK354(A)	GaAs-N-FET	UHF, C-Band, 5V, 150mA, 8GHz	52(SGSD)	Nec	—
2SK355	MOS-N-FET-e	V-MOS, 150V, 12A, 120W, <0,18Ω(10A)	23a	Tos	BUZ35, 2SK401, 2SK1529
2SK356	MOS-N-FET-e	V-MOS, 250V, 12A, 120W, <0,25Ω(10A)	23a	Tos	BUZ64, BUZ325, 2SK401, 2SK412
2SK357	MOS-N-FET-s	V-MOS, 150V, 5A, 40W, <0,9Ω(3A)	17p	Tos	BUZ60, 2SK924, 2SK1391
2SK358	MOS-N-FET-e	V-MOS, 250V, 5A, 40W, <1Ω(3A)	17p	Tos	BUZ60, 2SK924, 2SK1391
2SK359	MOS-N-FET-d	VHF, 20V, ±30mA, Idss>4mA, Up<2V	7f	Hit	—
2SK380	MOS-N-FET-d	=2SK359: SMD	35c,35d	Hit	—
2SK382	N-FET	Uni, 50V, Idss>1,2mA, Up<1,5V	7a	Tos	2SK183, 2SK385
2SK363	N-FET	Uni, 40V, Idss>5mA, Up<1,2V	7a	Tos	2N5247, 2SK130, 2SK147, 2SK151, 2SK162
2SK364	N-FET	Uni, 40V, Idss>2,6mA, Up<1,5V	7a	Tos	2SK187, 2SK366
2SK365	N-FET	=2SK382:	41a	Tos	2SK183, 2SK362
2SK366	N-FET	=2SK354:	41e	Tos	2SK187, 2SK364
2SK387	N-FET	Uni, ra, 100V, Idss>0,6mA, Up<3,5V	41a	Tos	—
2SK366	N-FET	=2SK387: SMD	35e	Tos	—
2SK369	N-FET	=2SK383: ra	7a	Tos	→2SK363
2SK37	N-FET	AM/FM, 20V, Idss=0,5..6mA, Up<4,5V	24e	Nec	BFS70, 2N3821, 2SK161
2SK370	N-FET	=2SK384: ra	41a	Tos	→2SK364
2SK371	N-FET	=2SK383: ra	41a	Tos	→2SK383
2SK372	N-FET	=2SK363:	41e	Tos	→2SK363
2SK373	N-FET	=2SK387:	7a	Tos	→2SK367
2SK374	N-FET	SMD, Uni, 55V, 30mA, Idss>1mA, Up<5V	35f	Mat	—
2SK375	MOS-N-FET-e	V-MOS, 300V, 1A, 10W, <4Ω, 20/70ns	30c	Hit	2SK535, 2SK945, 2SK1151, 2SK1672,++
2SK376	N-FET	NF-V, 20V, Idss=0,06..0,8mA	41e	Say	—
2SK377	N-FET	NF-V, 20V, Idss=0,06..0,8mA		Say	—

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2SK378	GaAs-N-FET	UHF, 5V, 130mA, Idss>15mA, Up<4V	24f	Mat	—
2SK379	MOS-N-FET-e	V-MOS, S-L, 400V, 8A, 100W, <1,5Ω	23a	Mat	BUZ94, 2SK278, 2SK298, 2SK554..555,++
2SK38	N-FET	S/Uni, 20V, Idss=0,45mA, Up<9V	≈42	Mit	BFS70, 2N3369, 2N3821, 2SK381,++
2SK380	MOS-N-FET-e	=2SK379: 450V, <2Ω	23a	Mat	BUZ94, 2SK554..555, 2SK638, 2SK1495,++
2SK381	N-FET	Uni, 50V, Idss>0,3mA, Up<6V	41a	Mit	2N3369
2SK382	MOS-N-FET-e	V-MOS, 500V, 2A, 30W, <4Ω, 25/70ns	17p	Hit	BUZ40, BUZ74, IRF820..821, 2SK892,++
2SK383	MOS-N-FET-e	V-MOS, 100V, 10A, 50W, <0,18Ω, 60/150ns	17p	Hit	BUZ20, BUZ72, IRF532, 2SK918, 2SK921+
2SK384	MOS-N-FET-e	V-MOS, 500V, 0,3A, 10W, <50Ω, 20/20ns	30p	Hit	—
2SK385	MOS-N-FET-e	V-MOS, 400V, 10A, 120W, <0,6Ω(5A)	77p	Tos	2SK693..694
2SK386	MOS-N-FET-e	=2SK385: 450V, <0,7Ω(5A)	77p	Tos	2SK693..694
2SK387	MOS-N-FET-e	V-MOS, S-L, 150V, 12A, 150W, <0,18Ω	77p	Tos	2SK1530
2SK388	MOS-N-FET-e	=2SK387: 250V, <0,25Ω(10A)	77p	Tos	2SK1530
2SK389	N-FET	Dual, 50V, Idss>2,6mA, Up<2V	7-SQP	Tos	—
2SK38A	N-FET	=2SK38: Idss=0,7..7mA, Up<5V	≈42		BFS70, 2N3369, 2N3821, 2SK381,++
2SK39(A)	N-FET	NF-V, ra, 20V, Idss=35..564A	10d	Son	2SK92..93, 2SK103
2SK393	MOS-N-FET-e	V-MOS, 100V, 10A, 100W, <0,25Ω(5A)	23a	Hit	BUZ23, 2SK631, 2SK633, 2SK1529
2SK399	MOS-N-FET-e	=2SK388.	18p	Hit	2SK631, 2SK633, 2SK1529
2SK40	N-FET	NF, ra, 50V, Idss=0,3..6,5mA, Up<5V	9a,7e	Hit	BFS70, 2N3369, 2N3821, 2SK48, 2SK59,++
2SK400	MOS-N-FET-e	V-MOS, 200V, 8A, 100W, <0,7Ω, 40/110ns	18p	Hit	2SK412
2SK401	MOS-N-FET-e	V-MOS, 250V, 10A, 100W, <0,4Ω, 65/180ns	23a	Hit	BUZ64, 2SK312..313, 2SK573, 2SK1401
2SK402	MOS-N-FET-e	V-MOS, 400V, 8A, 100W, <1,75Ω, 50/120ns	18p	Hit	BUZ330..331, BUZ353..354, 2SK501
2SK403	MOS-N-FET-e	=2SK402: 450V	18p	Hit	BUZ330..331, BUZ353..354, 2SK557
2SK404	N-FET	Uni, ra, 20V, Idss>1,2mA, Up<2V	40e	Say	BC264A, BFW12, 2N4340, 2N5484,++
2SK405	MOS-N-FET-e	V-MOS-L, 160V, 8A, 100W, <1,4Ω(5A)	18p	Tos	2SK1529
2SK406	GaAs-N-FET	UHF, C..Ku-Band, 5V, 120mA, 18GHz	52(SGSD)	Nec	—
2SK407	GaAs-N-FET	UHF, C..Ku-Band, 5V, 120mA, 18GHz	52(SGSD)	Nec	—
2SK408	MOS-N-FET-e*	V-MOS, AM-L, 180V, 2A, PQ>10W(28MHz)	17d	Hit	—
2SK409	MDS-N-FET-e	=2SK408.	17f	Hit	—
2SK41	N-FET	FM, 18V, Idss>0,8mA, Up<5V	7d	Say,Mic	BFS70, 2N3821, 2N5246, 2SK161,++
2SK410	MOS-N-FET-e*	V-MOS, AM-L, 160V, 8A, PEP>140W(28MHz)	57(SGSD)	Hit	—
2SK411	MOS-N-FET-e	V-MOS, 600V, 5A, 100W	23a	Hit	BUZ54, BUZ84, 2SK351, 2SK793, 2SK1403+
2SK412	MOS-N-FET-e	V-MOS, 250V, 10A, 100W, <0,4Ω, 65/180ns	18p	Hit	BUZ326, BUZ351, 2SK573, 2SK1401
2SK413	MOS-N-FET-e	V-MOS, 140V, 8A, 100W, <0,5Ω, 50/110ns	18p	Hit	2SK400, 2SK405, 2SK631, 2SK633
2SK414	MOS-N-FET-e	=2SK413: 180V	18p	Hit	2SK400, 2SK405, 2SK633
2SK415	MDS-N-FET-e	V-MOS, 600V, 3A, 100W, <8Ω, 50/120ns	18p	Hit	BUZ307, 25K603, 2SK954, 2SK1339
2SK416	MDS-N-FET-e	V-MOS, 40V, 2A, 10W, <0,8Ω(1A), 25/35ns	30p	Hit	2SK482, 2SK466, 2SK1282, 2SK1973,++
2SK417	MOS-N-FET-e	V-MOS-L, 60V, 10A, 60W, <0,14Ω	≈15p	Tos	BUZ20, BUZ72, 2SK442, 2SK872
2SK418	MOS-N-FET-e	V-MOS, S-L, 400V, 2A, 50W, <2,2Ω	≈15p	Tos	BUZ40, IRF710, 2SK382, 2SK892
2SK419	MOS-N-FET-e	=2SK418. 450V, <2,5Ω	≈15p	Tos	BUZ40, 2SK382, 2SK692
2SK41NP	N-FET	=2SK41:	7f		—
2SK42	N-FET	AM/FM, 10V, Idss=15mA, Up>0,3V	10d	Son	2N5246, 2SK107, 2SK181
2SK420	MOS-N-FET-e	V-MOS, S-L, 400V, 5A, 60W, <1,4Ω	≈15p	Tos	BUZ41A..42, 2SK552..553, 2SK1440,++
2SK421	MOS-N-FET-e	=2SK420. 450V, <1,6Ω	≈15p	Tos	BUZ41A..42, 2SK652..553, 2SK1440,++
2SK422	MOS-N-FET-e	V-MOS, 80V, 0,7A, 0,9W, <2,8Ω, 17/12ns	7c(9mm)	Tos	BST70, 2SK940..941, 2SK975
2SK423	MOS-N-FET-e	V-MOS, 100V, 0,5A, 0,9W, <4,5Ω, 15/20ns	7c(9mm)	Tos	BSS296, 2SK941
2SK424	MOS-N-FET-e	V-MOS, S-L, 600V, 3A, 100W, <1,5Ω(2A)	23a	Nec	BUZ53, BUZ83
2SK425	N-FET	SMD, 50V, Idss>1mA, Up<1,2V	35f	Nec	—
2SK426	N-FET	=2SK425: ra	35f	Nec	—
2SK427	N-FET	AM-VM/O, 15V, Idss>1,2mA, Up<1,5V	40e	Say	2SK166
2SK428	MOS-N-FET-e	V-MOS, 60V, 10A, 50W, <0,15Ω, 60/120ns	17c	Hit	BUZ20, BUZ72, IRF533, 2SK442, 2SK672+
2SK429(L,S)	MOS-N-FET-e	V-MOS, 100V, 3A, 20W, <0,7Ω, 35/50ns	30c	Hit	2SK1113, 2SK1299, 2SK1254, 2SK1284
2SK43(8)	N-FET	NF/Uni, ra, 30V, Idss>0,9mA, Up<1,49V	7d,7e	Son	2SK121, 2SK163, 2SK170, 2SK188..187,++
2SK430(L,S)	MOS-N-FET-e	=2SK429: 150V, <1Ω(2A)	30p	Hit	2SK1335
2SK431	N-FET	SMD, NF, ra, 40V, Idss>2,5mA, Up<1,5V	35f, 35e	Hit	—
2SK432	MOS-N-FET-e	V-MOS, S-L, 250V, ±10A, 120W, <0,4Ω	23a	Nec	BUZ45, BUZ64, 2SK401, 2SK512
2SK433	N-FET	SMD, 50V, Idss>0,3mA, Up<6V	35f	Mit	—
2SK435	N-FET	NF/HF, 22V, 0,1A, Idss>6mA, Up<2,5V	7d	Hit	2SK494
2SK436	N-FET	=2SK427: SMD	35f	Say	2SK425
2SK437	GaAs-N-FET	UHF, 6V, Idss>20mA, Up<3,5V, 12GHz	52(SGSD)	Mat	—
2SK438	GaAs-N-FET	UHF, 6V, Idss>20mA, Up<3,5V, 12GHz	52(SGSD)	Mat	—
2SK439	MOS-N-FET-d	FM/VHF, 20V, 30mA, Idss>4mA, Up<2V	41f	Hit	—
2SK44	N-FET	NF, ra, 20V, Idss=0,08..0,3mA, Up<4V	≈7e	Say	—
2SK440	MOS-N-FET-e	V-MOS, 200V, 8A, 40W, <0,5Ω, 40/110ns	17p	Hit	BUZ30, BUZ73, 2SK741, 2SK1319..20,++
2SK441	MOS-N-FET-e	V-MOS, 500V, 0,3A, 0,75W, <50Ω	2a	Hit	(2SK384)
2SK442	MOS-N-FET-e	V-MOS-L, 70V, 10A, 30W, <0,4Ω	17p	Tos	BUZ20, BUZ72, 2SK740, 2SK918
2SK443	N-FET	=2SK444: SMD	35f	Say	BF512..513, 2SK322

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2SK444	N-FET	Camera, ra, 15V, Idss=5..38mA, Up<2V	40e	Say	BC264C..D, BF410C..D, 2SK147, 2SK168
2SK445	N-FET	=2SK444:	7d	Say	BC264C..D, BF410C..D, 2SK147, 2SK168
2SK446	MOS-N-FET-e	V-MOS-L, 20V, ±2A, 20W, <0,5Ω(3A)	30p	Nec	2SK416, 2SK973, 2SK1763
2SK447	MOS-N-FET-e	V-MOS-L, 250V, ±15A, 150W, <0,24Ω(15A)	77p	Tos	2SK678, 2SK693
2SK448	MOS-N-FET-e	V-MOS, S-L, 250V, ±10A, 120W, <0,5Ω	23a	Nec	BUZ64, 2SK312, 2SK401
2SK449	MOS-N-FET-e	V-MOS, S-L, 450V, ±8A, 120W, <1,25Ω	23a	Nec	BUZ45, 2SK312, 2SK512
2SK44SP	N-FET	=2SK44:	41b		—
2SK45	N-FET	NF/HF, 22V, Idss=0,5..6mA, Up<4,5V	5m	Nec	BFS70, 2N3369, 2N3821, 2N4220, 2SK104+
2SK453	MOS-N-FET-e	V-MOS, VHF-L, 100V, 10A, PQ=120W(100MHz)	57(SGSD)	Nec	—
2SK454	MOS-N-FET-e	V-MOS, VHF-L, 200V, 8A, PQ=140W(100MHz)	57(SGSD)	Nec	—
2SK455	N-FET	=2SK456: SMD	=351	Tos	—
2SK456	N-FET	NF-V, 20V, Idss>0,06mA, Up<0,8V		Tos	—
2SK457	GaAs-N-FET	UHF, 5V, 120mA, Idss>20mA, Up<5V, 3GHz	25(GS	Hit	—
2SK456	MOS-N-FET-e	V-MOS, 150V, ±1A, 16W(Tc=25°), <1,5Ω	2a	Nec	—
2SK459	MOS-N-FET-e	V-MOS-L, 200V, ±10A, 60W, <0,5Ω(3A)	17p	Nec	BUZ31..32, 2SK890, 2SK925, 2SK1393,++
2SK46	N-FET	NF-V, ra, 30V, Idss=0,3..3mA, Up<5V	41e	Mit	BFS70, 2N3369, 2N3821, 2N4220, 2SK59,+
2SK462	MOS-N-FET-e	V-MOS-L, 60V, ±2A, 20W, <0,5Ω(1A)	30p	Nec	2SK468, 2SK612, 2SK973, 2SK1282
2SK463	MOS-N-FET-e	V-MOS-L, 60V, ±5A, 40W, <0,3Ω(3A)	17p	Nec	2SK294..295, 2SK346, 2SK357, 2SK917
2SK464	MOS-N-FET-e	V-MOS-L, 60V, ±8A, 50W, <0,2Ω(4A)	17p	Nec	IRF521, IRF523, 2SK470, 2SK993
2SK468	MOS-N-FET-e	V-MOS-L, 100V, ±2A, 20W	30p	Nec	2SK429..430, 2SK612, 2SK1113, 2SK1299,+
2SK47	N-FET	Uni, 20V, Idss=0,5 6mA, Up<4,5V	7e	Nec	BFS70, 2N3369, 2N3821, 2N4220, 2SK104+
2SK470	MOS-N-FET-e	V-MOS-L, 100V, ±8A, 50W, <0,3Ω(4A)	17p	Nec	BUZ30, BUZ73, IRF520, IRF522
2SK477	MOS-N-FET-e	V-MOS-L, 250V, ±8A, 60W, <0,8Ω(3A)	17p	Nec	2SK319..20, 2SK1400, 2SK1667
2SK479	MOS-N-FET-e	V-MOS, S-L, 250V, ±15A, 100W, <0,4Ω	16p	Nec	2SK559, 2SK573, 2SK1135, 2SK1401
2SK46	N-FET	NF, ra, 20V, Idss=0,3..3mA, Up<2,3V	5n	Tos	BF410A, 2N4339, 2N5358, 2SK193,++
2SK482	MOS-N-FET-e	V-MOS, S-L, 450V, ±5A, 50W, <2Ω(2A)	17p	Nec	BUZ41A..42, IRF830, 2SK1246, 2SK1440++
2SK484	MOS-N-FET-e	V-MOS, S-L, 450V, ±8A, 100W, <1Ω	16p	Nec	BUZ330..331, 2SK559, 2SK634, 2SK1468,++
2SK49	N-FET	AM/FM, 20V, Idss=0,5..6mA, Up<2,5V	7f	Nec	BF410A, 2SK193, 2SK195, 2SK212
2SK490	MOS-N-FET-e	V-MOS, S-L, 400V, ±10A, 100W, <0,8Ω	16p	Nec	BUZ325..326, 2SK559, 2SK634, 2SK1468,++
2SK492	N-FET	SMD, Uni, 50V, Idss>1mA, Up<2V	35f	Mit	—
2SK493	N-FET	Uni, 15V, Idss>5mA, Up<2,2V	7d	Say	BC264C..D, BF410C..D, 2SK147, 2SK168
2SK494	N-FET	=2SK435:	41a	Hil	→2SK435
2SK495	MOS-N-FET-e	V-MOS-L, 60V, 5A, 40W, <0,3Ω, 30/40ns	17p	Mat	2SK346, 2SK463, 2SK917, 2SK920
2SK496	MOS-N-FET-e	=2SK495: Iso	17c	Mat	BUK441-60, 2SK499, 2SK705, 2SK1255
2SK497	MOS-N-FET-e	V-MOS-L, 50V, 5A, 40W, <0,25Ω, 30/40ns	17p	Mat	2SK346, 2SK463, 2SK917, 2SK920
2SK496	MOS-N-FET-e	=2SK497:	30	Mat	2SK1059, 2SK1112, 2SK1471, 2SK1719,++
2SK499	MOS-N-FET-e	=2SK497: Iso	17c	Mat	BUK441-60, 2SK496, 2SK705, 2SK1255
2SK50	N-FET	NF-V, ra, 10V, Idss=0,07..1mA	7e	Mat, Mic	2N3367, 2N4117..18, 2SK92..93, 2SK103,++
2SK500	MOS-N-FET-e	V-MOS-L, 60V, 10A, 80W, <0,12Ω	16p	Mat	2SK399, 2SK631
2SK501	MOS-N-FET-e	V-MOS-L, 400V, 8A, 60W, <1,2Ω, 55/40ns	16p	Mat	BUZ330..331, BUZ385
2SK502	MOS-N-FET-e	V-MOS-L, 400V, 3A, 40W, <4Ω, 35/15ns	17p	Mat	BUZ76, 2SK310..311, 2SK1244
2SK503	MOS-N-FET-e	=2SK502: Iso	17c	Mal	BUK445-450, 2SK1444, 2SK1682..63,++
2SK505	N-FET	Video, 15V, Idss>10mA, Up<3,5V	7d	Nec	2SK507
2SK507	N-FET	=2SK505:	40e	Nec	2SK505
2SK508	N-FET	=2SK505: SMD	35f	Nec	—
2SK511	MOS-N-FET-e*	V-MOS, Vid, 250V, 0,3A, 8W, <50Ω(0,1A)	14b(j)	Hit	—
2SK512	MOS-N-FET-e	V-MOS, 500V, 12A, 125W, <0,65Ω, 75/300ns	23a	Hit	BUZ45, 2SK1785
2SK513	MOS-N-FET-e	V-MOS, 800V, 3A, 60W, <6Ω, 50/120ns	17p	Hit	BUK456/800, 2SK1600..1601, 2SK1638,++
2SK514	N-FET	Analog-S, 50V, 20mA, Idss>1mA, Up<4,5V	40e	Nec	—
2SK515	N-FET	=2SK514: SMD	35f	Nec	—
2SK518	N-FET	AM-Tuner, 30V, 0,05A, Idss>30mA, Up<9V	7a	Nec	BF2440, BF2450, 2SK519
2SK519	N-FET	=2SK516:	40a	Nec	BD2440, BF2450, 2SK518
2SK520	N-FET	=2SK518: SMD	35f	Nec	BF545C
2SK521	N-FET	FM/VHF-M/O, 16V, Idss>2mA, Up<5,5V	41f	Hit	2SK107, BFS71, 2N3822
2SK522	N-FET	FM/VHF-M/O, 30V, Idss>4mA, Up<3V	41f	Hit	BF410C
2SK523	N-FET	NF, ra, 50V, 30mA, Idss>1mA, Up<1,2V	7d	Nec	—
2SK525	MOS-N-FET-e	V-MOS, 150V, 10A, 40W, <0,28Ω(5A)	17c	Tos	2SK1035..1038
2SK526	MOS-N-FET-e	V-MOS, 250V, 10A, 40W, <0,8Ω(5A)	17c	Tos	2SK1036, 2SK1762
2SK527	MOS-N-FET-e	V-MOS, 60V, 10A, 40W, <0,14Ω(5A)	17c	Tos	BUK442/60, 2SK1033, 2SK1093, 2SK1974,++
2SK528	MOS-N-FET-a	V-MOS, S-L, 400V, 2A, 30W, <2,2Ω(1A)	17c	Tos	BUK444-400, 2SK1833, 2SK1988..89,++
2SK529	MOS-N-FET-e	=2SK526: 450V, <2,6Ω(1A)	17c	Tos	BUK444-450, 2SK1833, 2SK1968..89,++
2SK530	MOS-N-FET-e	V-MOS, S-L, 400V, 5A, 40W, <1,4Ω(3A)	17c	Tos	2SK1231..32, 2SK1608, 2SK1990..91,++
2SK531	MOS-N-FET-e	=2SK530: 450V, <1,6Ω(3A)	17c	Tos	2SK1231..32, 2SK1608, 2SK1990..91,++
2SK532	MOS-N-FET-e	V-MOS, 60V, 12A, 40W, <0,085Ω(8A)	17c	Tos	BUK445-100, 2SK1094, 2SK1419
2SK533	N-FET	=2SK523: Igss<100pA	7d	Nec	—
2SK534	MOS-N-FET-e	V-MOS, 600V, 5A, 100W, <4Ω, 75/220ns	18p	Hit	BUZ355..358, 2SK695, 2SK793, 2SK1341,++

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2SK535(L,S)	MOS-N-FET-e	V-MOS, 400V, 1,5A, 20W, <6Ω, 20/45ns	30p	Hit	2SK579..80, 2SK945, 2SK1151..52, 2SK1672
2SK536	MOS-N-FET-e	SMD, Analog-S, 50V, 100mA, 20Ω	35e	Say	—
2SK537	MOS-N-FET-e	V-MOS, S-L, 900V, 1A, 60W, <9Ω(0,5A)	17p	Tos	BUZ50, 2SK1199, 2SK1338
2SK538	MOS-N-FET-e	V-MOS, S-L, 900V, 3A, 100W, <4,5Ω(1,5A)	18p	Tos	BUZ357..358, 2SK794, 2SK1339
2SK539	MOS-N-FET-e	V-MOS, S-L, 900V, 5A, 150W, <2,5Ω(3A)	77p	Tos	—
2SK54	N-FET	FM-V/M, 15V, Idss=0,65mA, Up<5,5V	9f,7f	Hit	BF410A, BFS70, 2N3821, 2SK212,++
2SK541	N-FET	Video-Camera, 12V, Idss>14mA, Up<2,5V	35f	Hit	—
2SK542	MOS-N-FET-e	V-MOS, S-L, 150V, ±2A, 25W, <1,5Ω(1A)	17p	Nec	IRF612..613, 2SK923
2SK543	MOS-N-FET-d	=2SK544: SMD	35e	Say	—
2SK544	MOS-N-FET-d	FM/VHF, 20V, 30mA, Idss>1,2mA, Up<2,5V	40e,d	Say	2SK192
2SK545	N-FET	=2SK546: SMD	35f	Say	—
2SK546	N-FET	h-ohm, 40V, Idss>0,03mA, Up<4V	40e	Say	—
2SK549	MOS-N-FET-e	V-MOS, 80V, 10A, 50W, <0,15Ω, 55/100ns	17p	Hit	BUZ20, BUZ72, IRF532..33, 2SK1114,++
2SK55	N-FET	FM-VM, 18V, Idss=3..14mA, Up<5,5V	9f,7f	Hit	BF244..245, BFS71, 2N3822..23, 2SK107,++
2SK550	MOS-N-FET-e	V-MOS, 60V, 25A, 75W, <0,045Ω, 115/245ns	17p	Hit	BUZ21, IRF541, IRF543, 2SK1115..16,++
2SK551	MOS-N-FET-e*	V-MOS, 120V, 10A, 50W, <0,2Ω, 55/100ns	17p	Hit	BUZ31..32, 2SK459, 2SK720, 2SK890
2SK552	MOS-N-FET-e*	V-MOS, 450V, 5A, 50W, <1,4Ω, 45/115ns	17p	Hit	BUZ41..42, BUZ90, IRF830, 2SK1246,++
2SK553	MOS-N-FET-e*	=2SK552: 500V	17p	Hit	BUZ41..42, BUZ90, IRF830, 2SK1246,++
2SK554	MOS-N-FET-e*	V-MOS, 450V, 7A, 60W, <0,85Ω, 65/155ns	17p	Hit	BUK657-500, IRF840, 2SK894, 2SK1496,++
2SK555	MOS-N-FET-e*	=2SK554: 500V, <1Ω(4A)	17p	Hit	BUK657-500, IRF840, 2SK894, 2SK1496,++
2SK556	MOS-N-FET-e*	V-MOS, 450V, 12A, 100W, <0,55Ω(6A)	18p	Hit	2SK725, 2SK899, 2SK1610, 2SK1745,++
2SK557	MOS-N-FET-e*	=2SK556: 500V, <0,6Ω(6A)	18p	Hit	2SK725, 2SK899, 2SK1610, 2SK1745,++
2SK558	MOS-N-FET-e	V-MOS, S-L, 500V, 12A, 100W, 85/300ns	18p	Hit	2SK557, 2SK560, 2SK1516, 2SK1753,++
2SK559	MOS-N-FET-e*	V-MOS, 450V, 15A, 100W, <0,36Ω(6A)	18p	Hit	2SK725, 2SK899, 2SK1745, 2SK1757,++
2SK56	N-FET	FM/VHF, 10V, Idss=0,7..10mA, Up<4V	7f	Mat, Mic	BF410A, BFS70, 2N3821, 2SK161,++
2SK560	MOS-N-FET-e*	=2SK559: 500V, 0,4Ω(8A)	18p	Hit	2SK725, 2SK899, 2SK1745, 2SK1757,++
2SK561	MOS-N-FET-e	V-MOS, 100V, 30A, 150W, <0,07Ω	23a	Hit	BUZ24, 2N6764, 2SK906, 2SK1303,++
2SK562	MOS-N-FET-e	V-MOS, S-L, 50V, 39A, 125W, <0,04Ω	18p	Fjd	BUZ347..348, 2SK857, 2SK905, 2SK1124,++
2SK564	MOS-N-FET-e	V-MOS, S-L, 100V, 32A, 125W, <0,06Ω	18p	Fjd	BUZ349, 2SK906, 2SK1303, 2SK1433
2SK565	MOS-N-FET-e	V-MOS, S-L, 500V, 9,6A, 125W, <0,6Ω	18p	Fjd	2SK557, 2SK637, 2SK1516, 2SK1753,++
2SK566	MOS-N-FET-e	V-MOS, S-L, 800V, 2,9A, 78W, <4Ω	18p	Fjd	2SK415, 2SK538, 2SK603, 2SK762
2SK566	MOS-N-FET	V-MOS, S-L, 450V, ±8A, 150W, <0,75Ω	77p	Tos	—
2SK569	GaAs-N-FET-d	UHF, C..Ku-Sand, 6V, Idss>15mA, Up<2V	52(SGSD)	Nec	—
2SK57	N-FET	SMD, 20V, 20mA, Idss=0,5..6mA, Up<4V	35f	Nec	BF510, 2SK180
2SK570(S)	GaAs-N-FET-d	UHF, C..Ku-Sand, 6V, Idss>2mA, Up<2V	52(SGSD)	Nec	—
2SK571	GaAs-N-FET-d	UHF, C-Band, 5V, Idss=30..150mA	52(SGSD)	Nec	—
2SK572	MOS-N-FET-e	V-MOS, 150V, 15A, 100W, <0,18Ω(10A)	18p	Tos	BUZ350, 2SK622, 2SK1267, 2SK1491,++
2SK573	MOS-N-FET-e	V-MOS, 250V, 15A, 100W, <0,32Ω(10A)	18p	Tos	BUZ323, 2SK944, 2SK1401, 2SK1641,++
2SK575	GaAs-N-FET-d	UHF, Ku-Band, 5V, Idss>5, Up<3V, 12GHz	52(SGSD)	Son	—
2SK578	MOS-N-FET-e	V-MOS, S-L, 150V, ±15A, 120W, <0,22Ω	77p	Tos	—
2SK579(L,S)	MOS-N-FET-e*	V-MOS, 450V, 1,5A, 20W, <5,5Ω, 28/46ns	30p	Hit	2SK1151..52, 2SK1672
2SK58	N-FET	Dual, 27V, Idss=1..16,5mA, Up<4,95V	6-DIP	Son	—
2SK580(L,S)	MOS-N-FET-e*	=2SK579: 500V, <6Ω(1A)	30p	Hit	2SK1152, 2SK1672
2SK581	N-FET	HF, ra, 30V, Idss>0,9mA, Up<1,49V	41e	Son	—
2SK582	N-FET	VHF/UHF, 30V, Idss>40mA, Up<6V, 500MHz	41e	Son	—
2SK583	MOS-N-FET-e	V-MOS, Analog-S, 50V, 0,2A, 0,6W, 20Ω	7d	Say	BSS100, BST72
2SK585	GaAs-N-FET-d	UHF, X-Band, 5V, Idss>20mA, Up<4V, 12GHz	25	Son	—
2SK586	GaAs-N-FET-d	UHF, Ku-Band, 5V, Idss>2mA, Up<3V, 12GHz	52(SGSD)	Son	—
2SK587	GaAs-N-FET-d	UHF, X-Band, 5V, Idss>2mA, Up<3V, 12GHz	25	Son	—
2SK59	N-FET	NF-V, ra, 30V, Idss=0,3..1,4mA, Up<5V	9a	Hit	BFS70, 2N3821, 2N4220, 2SK46, 2SK104,++
2SK590	GaAs-N-FET-d	VHF/UHF, 10V, Idss>20mA, Up<4V, 1GHz	25(GSDS)	Tos	—
2SK591	MOS-N-FET-e	V-MOS, LogL, 60V, ±15A, 35W, <55mΩ(6A)	17c	Nec	2SK1094
2SK593	GaAs-N-FET-d	VHF/UHF, 5V, Idss>15mA, Up<4V, 800MHz	25(G-OS)	Mat	—
2SK595	N-FET	=2SK596: SMD	≈35f	Say	—
2SK596	N-FET	Kondsns.-Mikr.-V, 20V, Idss>0,1..0,8mA	41e	Say	XSK596
2SK597	N-FET	=2SK596		Say	—
2SK60	N-FET	V-FET-L, 170V, 5A, 63W, 16Ω	23a	Son	—
2SK600	MOS-N-FET-e	V-MOS, 60V, 25A, 75W, <0,055Ω	17p	Hit	BUZ21, IRF540..543, 2SK942, 2SK1115,++
2SK601	MOS-N-FET-e	V-MOS, S, 80V, 0,5A, IW, <4Ω, 15/20ns	39b	Mat	BST80, 2SK1078..1079
2SK602	MOS-N-FET-e	V-MOS, S-L, 800V, 1A, 40W, <8Ω	17c	Mat	BUZ78, 2SK537
2SK603	MOS-N-FET-e	V-MOS, S-L 800V, 3A, 60W, <5Ω	16c(p)	Mat	BUZ307, 2SK415, 2SK954
2SK604	MOS-N-FET-e	V-MOS, S-L, 800V, 5A, 80W, <3,5Ω	16c(p)	Mat	BUZ355..357, 2SK534, 2SK695, 2SK793,+
2SK606	N-FET	FM-Tuner, 30V, 20mA, Idss>0,5mA, Up<3V	7f	Mat	2SK193, 2SK195
2SK607	N-FET	=2SK606:	40d	Mat	2SK193, 2SK195
2SK608	N-FET	=2SK606: SMD	35c	Mat	(2SK238)
2SK609	GaAs-N-FET-d	UHF, C..Ku-Band, 6V, Idss>20mA, Up<3,5V	51(SGSD)	Nec	—

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2SK61	N-FET	FM/VHF, 18V, Idss=1..10mA, Up<4V	7d	Tos	BF244A..245A, BFS71, 2N3822..23, ++
2SK610	MOS-N-FET-e	V-MOS, S-L, 400V, 3A, 80W, <4Ω	16c(p)	Mat	BUZ307, 2SK415, 2SK635, 2SK954
2SK611(Z)	MOS-N-FET-e	V-MOS, S-L, 100V, ±1A, 10W, <5Ω(0,5A)	30p	Nec	2SK468
2SK612(Z)	MOS-N-FET-e	V-MOS, S-L, 100V, ±2A, 20W, <0,45Ω(1A)	30p	Nec	2SK468, 2SK429..30, 2SK1283
2SK613	N-FET	SMD, Camera, 15V, Idss>13,4mA, Up<2V	35f	Son	—
2SK614	MOS-N-FET-e	V-MOS, 80V, 0,5A, 0,75W, <4Ω, 15/20ns	7c	Mat	BST70, 2SK423, 2SK940..941
2SK615	MOS-N-FET-e	=2SK614: 1W	9c	Mat	BST70, 2SK423, 2SK940..941
2SK616	MOS-N-FET-e	V-MOS, S-L, 200V, 22A, 125W, <0,12Ω	18p	Fjd	BUZ350, 2SK1491, 2SK2007, 2SK2058, ++
2SK617	MOS-N-FET-e	V-MOS, S-L, 800V, 1A, 40W, <8Ω		Mel	—
2SK618	GaAs-N-FET-d	SMD, VHF/UHF, 10V, Idss>20mA, Up<4V	35e	Tos	—
2SK619	MOS-N-FET-e*	V-MOS, HF, Video, 70V, 0,3A, 10W	14t(S=case)	Hit	—
2SK620	MOS-N-FET-e	SMD, int. Diode(S→G), V-MOS, 50V, 0,1A	35e	Mat	—
2SK621	MOS-N-FET-e	SMD, int. Di+R(S→G), V-MOS, 20V, 0,1A	35a	Mat	—
2SK622	MOS-N-FET-e*	V-MOS, 150V, 20A, 120W, <75mΩ(10A)	18p	Hit	BUZ350, 2SK1267, 2SK1491, 2SK2007, ++
2SK623	MOS-N-FET-e*	V-MOS, 250V, 20A, 120W, <0,15Ω(10A)	18p	Hit	2SK1491, 2SK2007, 2SK2058, 2SK2075, ++
2SK624	N-FET	NF-V, ra, 20V, 2mA, Idss=95..385µA	40e	Mat	—
2SK625	N-FET	SMD, Kond.-Mikrof., 20V, Idss>0,06mA	35f	Tos	—
2SK626	MOS-N-FET-e	V-MOS, S-L, 30V, 20A, 80W, <0,07Ω	16c(p)	Mat	BUZ350
2SK627	MOS-N-FET-e	=2SK626: 50V	16c(p)	Mat	BUZ350
2SK628	MOS-N-FET-e	V-MOS, S-L, 100V, 5A, 40W, <0,4Ω	17c	Mel	BUK442-100, BUK542-100, 2SK992, ++
2SK629	MOS-N-FET-e	V-MOS, S-L, 100V, 20A, 80W, <0,1Ω	16c(p)	Mat	2SK622
2SK63	N-FET	V-FET, 120V, 0,2A, 0,47W, Up<9,5V	2a	Son	—
2SK630	MOS-N-FET-e	V-MOS, S-L, 160V, 5A, 40W, <0,5Ω	16c(p)	Mat	—
2SK631	MOS-N-FET-e	V-MOS, S-L, 180V, 10A, 80W, <0,2Ω	16c(p)	Mat	2SK633
2SK632	MOS-N-FET-el	V-MOS, S-L, 200V, 5A, 40W, <1,2Ω	16c(p)	Mat	—
2SK633	MOS-N-FET-e	V-MOS, S-L, 200V, 10A, 80W, <0,25Ω	16c(p)	Mat	2SK412
2SK634	MOS-N-FET-e	V-MOS, S-L, 400V, 10A, 80W, <0,7Ω	16c(p)	Mat	BUZ326, BUZ351, 2SK559
2SK635	MOS-N-FET-e	V-MOS, S-L, 500V, 3A, 40W, <4,5Ω	16c(p)	Mat	BUZ307, 2SK415, 2SK954
2SK636	MOS-N-FET-e	V-MOS, S-L, 500V, 8A, 80W, <1,4Ω	16c(p)	Mat	BUZ330..331, BUZ353..354
2SK637	MOS-N-FET-e	V-MOS, S-L, 500V, 10A, 80W, <1,4Ω	16c(p)	Mat	2SK557, 2SK644, 2SK1468, 2SK1753, ++
2SK638	MOS-N-FET-e	V-MOS, S-L, 800V, 3A, 80W, <5Ω	18p	Mel	BUZ307, 2SK415, 2SK538, 2SK603
2SK641	MOS-N-FET-e*	V-MOS, 450V, 10A, 100W, <0,8Ω(5A)	18p	Hit	BUZ339, 2SK896, 2SK1498, 2SK1752, ++
2SK642	MOS-N-FET-e*	=2SK641: 500V, <1Ω(5A)	18p	Hit	BUZ339, 2SK896, 2SK1468, 2SK1753, ++
2SK643	MOS-N-FET-e	V-MOS, 450V, 10A, 125W, <0,8Ω(5A)	18p	Tos	BUZ339, 2SK896, 2SK1468, 2SK1752, ++
2SK644	MOS-N-FET-e	=2SK643: 500V, <1Ω(5A)	18p	Tos	BUZ339, 2SK896, 2SK1468, 2SK1753, ++
2SK645	N-FET*	Mikrofon-V, 15V, Zin>200MΩ, Ur<40mV		Tos	—
2SK646	MOS-N-FET-e	V-MOS, 1200V, 4A, 125W, <4Ω, 80/350ns	23a	Hit	—
2SK647	GaAs-N-FET	UHF, 6V, 120mA, Idss=20..120mA, 12GHz	51(SGSD)	Mat	—
2SK648	GaAs-N-FET	UHF, 6V, 120mA, Idss=20..120mA, 12GHz	51(SGSD)	Mat	—
2SK649	GaAs-N-FET	UHF, Ku-Band, 6V, 0,1A, 12GHz	51(SGSD)	Mat	—
2SK65	N-FET	NF-V, ra, 12V, 2mA, Idss=0,04..0,8mA	9e	Mat	—
2SK650	GaAs-N-FET	UHF, 6V, 120mA, Idss=20..120mA, 4GHz	25(GSDS)	Mat	—
2SK651	GaAs-N-FET	UHF, 8V, 150mA, Idss=40..150mA, 4GHz	25(GSDS)	Mat	—
2SK652	N-FET	=2SK301:	40e	Mat	→2SK301
2SK653	GaAs-N-FET	SMD, UHF, 5V, 70mA, 800MHz	44	Mat	—
2SK654(Z)	MOS-N-FET-e	V-MOS, S-L, 100V, ±1A, 10W, <3Ω(0,5A)	30p	Nec	2SK468, 2SK611..612
2SK655	MOS-N-FET-e	=2SK620:	40b	Mat	—
2SK656	MOS-N-FET-e	=2SK621:	40b	Mat	—
2SK657	MOS-N-FET-e	=2SK620:	9c	Mat	—
2SK658	MOS-N-FET-e	=2SK621:	9c	Mat	—
2SK659	MOS-N-FET-e	V-MOS, LogL, 80V, ±12A, 35W, <75mΩ(6A)	17c	Nec	2SK1033, 2SK1093, 2SK1258, 2SK1344
2SK66	N-FET	NF, ra, 55V, Idss>0,3mA, Up<5V	7e	Mat, M	BFS70, 2N3821, 2N4220, 2SK59, 2SK104, ++
2SK660	N-FET	Kond.-Mikrof-V, 20V, 10mA	40e	Nec	—
2SK662	N-FET	=2SK198:	35e(2mm)	Mat	—
2SK663	N-FET	=2SK374:	35a(2mm)	Mat	—
2SK654	MOS-N-FET-e	=2SK620:	35a(2mm)	Mat	—
2SK665	MOS-N-FET-e	=2SK621:	35a(2mm)	Mat	—
2SK666	GaAs-N-FET	VHF/UHF, 4V, 150mA, Idss>20mA, 900MHz	25(GSDS)	Hit	—
2SK667	MOS-N-FET-e	V-MOS, S-L, 400V, 8A, 80W, <1,5Ω	16c(p)	Mel	BUZ330..331, BUZ353..354, 2SK501
2SK668	GaAs-N-FET	=2SK457:	44(SDSG)	Hit	—
2SK669	MOS-N-FET-e	V-MOS, Analog-S, 50V, 0,1A, 0,2W, 20Ω	40e,d	Say	BSS100
2SK67(A)	N-FET	SMD, 20V, Idss=0,02..1mA, Up<0,8V	≈35b	Nec	—
2SK671	GaAs-N-FET	UHF, X-Band, 5,5V, 120mA, 12GHz	25	Son	—
2SK672	MOS-N-FET-e	V-MOS, 60V, 10A, 40W, <0,2Ω(5A)	17p	Tos	BUZ20, IRF532..533, 2SK918, 2SK1114, ++
2SK673	MOS-N-FET-e	V-MOS, 80V, 15A, 75W, <0,11Ω(8A)	17p	Tos	BUZ21, IRF530..531, 2SK971, 2SK1418, ++
2SK674	MOS-N-FET-e	V-MOS, 80V, 25A, 100W, <60mΩ(15A)	17p	Tos	BUK555-60, 2SK1296

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2SK676	GaAs-N-FET	UHF, K-Band, 5V, 70mA, 12GHz	52(SGSD)	Son	—
2SK677	GaAs-N-FET	UHF, K-Band, 5V, 100mA, 12GHz	51(SGSD)	Son	—
2SK678	MOS-N-FET-e	V-MOS, DC-DC, 500V, 13A, 150W, <0,4Ω	77	Tos	2SK1333
2SK679	MOS-N-FET-e*	V-MOS, S, 30V, ±0,5A, 0,75W, <1Ω(0,5A)	7b	Nec	BST70, 2SK422, 2SK940
2SK68(A)	N-FET	NF, 50V, Idss=0,5..12mA, Up<1,5V	7a	Nec	2SK106, 2SK121, 2SK163, 2SK170, 2SK184++
2SK680(A)	MOS-N-FET-e*	=2SK6S1: SMD, ±1A	39b	Nec	2SK1726
2SK681(A)	MOS-N-FET-e*	=2SK679: ±1A, 1W	9c	Nec	2SK975, 2SK1272, 2SK1274, 2SK1733
2SK682	MOS-N-FET-e*	FREDFET, 450V, 12A, 100W, <0,55Ω(6A)	18p	Hit	BUK638-500
2SK683	MOS-N-FET-e*	=2SK682: 500V, <0,6Ω(6A)	18p	Hit	BUK638-500
2SK684	MOS-N-FET-e*	V-MOS, 800V, 7A, 100W, <1,5Ω(4A)	18p	Hit	2SK1032, 2SK1358, 2SK1502, 2SK1614,++
2SK685	MOS-N-FET-e*	FREDFET, 1000V, 5A, 100W, <2Ω(3A)	18p	Hit	BUK638-1000, BUZ380..381
2SK686	MOS-N-FET-e	V-MOS, S-L, 60V, 5A, 40W, <0,3Ω(2,5A)	17p	Say	2SK294, 2SK346, 2SK463, 2SK917,++
2SK687	MOS-N-FET-e	V-MOS, S-L, 60V, 10A, 60W, <0,18Ω(5A)	17p	Say	2SK442, 2SK549, 2SK672, 2SK970, 2SK1114
2SK688	MOS-N-FET-e	V-MOS, S-L, 60V, 15A, 60W, <0,12Ω(6A)	17p	Say	BUK552-60, 2SK673, 2SK971, 2SK1416
2SK689	GaAs-N-FET	UHF, 6V, 70mA, Idss=13..70mA, 4GHz	51(SGSD)	Mat	—
2SK69	N-FET	V-FET, NF, 140V, 0,1A, 0,8W	2a	Nec	—
2SK690	GaAs-N-FET	UHF, 2xint. Z-Di, 10V, 0,5A, 1GHz	39f	Mat	—
2SK681	GaAs-N-FET	UHF-L, 20V, 6,3A, 1GHz		Mat	—
2SK692	N-FET	Kondens.-Mikrof., 20V, Idss>0,06mA	40a	Nec	—
2SK693	MOS-N-FET-e	V-MOS, 450V, 13A, 150W, <0,4Ω(7A)	77p	Tos	2SK678, 2SK1333, 2SK1544
2SK694	MOS-N-FET-a	V-MOS, 500V, 12A, 150W, <0,5Ω(7A)	77p	Tos	2SK878, 2SK1333, 2SK1544
2SK695	MOS-N-FET-e*	V-MOS, 800V, 5A, 100W, <3Ω(3A)	18p	Hit	2SK793..94, 2SK727, 2SK1213, 2SK1403,++
2SK696	MOS-N-FET-e*	V-MOS, 1000V, 3A, 100W, <4Ω(2A)	18p	Hit	2SK727, 2SK794, 2SK1461, 2SK1649..50,++
2SK697	GaAs-N-FET	HF, 5V, Idss=15..50mA, 50MHz	44	Mat	—
2SK698	MOS-N-FET-e	V-MOS, S-L, 450V, ±10A, 120W, <0,8Ω	16p	Nec	2SK556..557, 2SK642, 2SK644, 2SK683,++
2SK699	MOS-N-FET-e	V-MOS, S-L, 100V, ±2A, 15W, <1,2Ω(1A)	14j	Nec	2SK1264
2SK70	N-FET	V-FET-L, 100V, 10A, 100W, Idss=3..6A	23a	Nec	—
2SK700	MOS-N-FET-e	=2SK699: 60V, <0,8Ω(1A)	14j	Nec	2SK1264
2SK701	MOS-N-FET-e	=2SK699: 60V, <0,6Ω(1A)	14j	Nec	2SK1283
2SK702	MOS-N-FET-e	V-MOS, LogL, 100V, ±5A, 50W, <0,45Ω(5A)	17p	Nec	2SK991
2SK703	MOS-N-FET-e	=2SK702: Iso, 35W	17c	Nec	BUK542-100, 2SK1260, 2SK1265
2SK704	MOS-N-FET-e	V-MOS, LogL, 60V, ±5A, 50W, <0,25Ω(5A)	17p	Nec	2SK702, 2SK991
2SK705	MOS-N-FET-e	=2SK704: Iso, 35W	17c	Nec	BUK541-60, 2SK1260, 2SK1255
2SK707	MOS-N-FET-e	V-MOS, 250V, ±25A, 120W, <0,15Ω(13A)	18p	Nec	2SK623, 2SK901, 2SK944, 2SK1641
2SK708	MOS-N-FET-e	V-MOS, S-L 450V, ±10A, 200W, <0,6Ω(10A)	77p	Tos	2SK678, 2SK693, 2SK694, 2SK1029
2SK709	N-FET	HF, AM, 20V, Idss=6..32mA, Up<2,5V	7d	Tos	2SK1000
2SK71	N-FET	V-FET-L, 160V, 15W, Idss=30..300	22a	Nec	—
2SK710	N-FET	=2SK709:	41a	Tos	—
2SK711	N-FET	=2SK709: SMD	35f	Tos	—
2SK712	MOS-N-FET-e	V-MOS, 120V, 10A, 25W, <0,2Ω	17c	Hit	2SK1035, 2SK1230, 2SK2212
2SK713	MOS-N-FET-e	V-MOS, 450V, 4A, 25W, <1,4Ω	17c	Hit	2SK1231..32, 2SK1351, 2SK1608, 2SK1626++
2SK714	MOS-N-FET-e	=2SK713: 500V	17c	Hit	2SK1232, 2SK1351, 2SK1608, 2SK1627,++
2SK715	N-FET	AM-Tuner, 15V, Idss=5..24mA, Up<1,4V	40e	Say	—
2SK719	MOS-N-FET-e	V-MOS, S-L, 900V, ±5A, 120W, <4Ω(3A)	18p	Nec	2SK727, 2SK1205, 2SK1461, 2SK1649..1650
2SK72	N-FET	Dual, VHF, 20V, Idss>0,6mA, Up<3,3V	TO-60	Tos	—
2SK720A	MOS-N-FET-e	V-MOS, 250V, ±20A, 120W, <0,23Ω(10A)	16p	Nec	2SK901, 2SK944, 2SK1641, 2SK1673..74,++
2SK722	MOS-N-FET-e	V-MOS, S-L, 170V, 10A, 100W	18c(p)	Son	2SK633
2SK723	MOS-N-FET-e	V-MOS, S-L, 500V, 7A, 125W, <1,2Ω	18p	Fjd	BUZ330..331, BUZ353..354, 2SK1032
2SK724	MOS-N-FET-e	V-MOS, S-L, 500V, 10A, 100W, <0,67Ω	18p	Fjd	2SK642, 2SK644, 2SK683, 2SK1753, 2SK1785
2SK725	MOS-N-FET-e	V-MOS, S-L, 500V, 15A, 125W, <0,38Ω	18p	Fjd	BUZ338, 2SK788, 2SK899, 2SK1610,++
2SK726	MOS-N-FET-e	V-MOS, S-L, 900V, 3A, 100W, <5Ω(1,5A)	18p	Fjd	2SK696, 2SK1339
2SK727	MOS-N-FET-e	V-MOS, S-L, 900V, 5A, 125W, <2,5Ω(2,5A)	18p	Fjd	2SK685, 2SK1461, 2SK1760, 2SK1794,++
2SK73	N-FET	NF-L, 200V, 0,1A, 5W, Idss<100mA	14a	Mel	—
2SK732	MOS-N-FET-e	V-MOS, S-L, 450V, 10A, 45W, <0,78Ω(5A)	17c	Mit	—
2SK733	MOS-N-FET-e	=2SK732: 120W	≈18p	Mit	BUZ339, 2SK896, 2SK1488, 2SK1785,++
2SK734	MOS-N-FET-e	V-MOS, S-L, 450V, 15A, 150W, <0,52Ω(6A)	≈18p	Mit	2SK1610, 2SK1878, 2SK1745, 2SK1757,++
2SK735	MOS-N-FET-e	V-MOS, 450V, ±10A, 100W, <0,8Ω(5A)	18p	Nec	BUZ339, 2SK696, 2SK1488, 2SK1785,++
2SK738	MOS-N-FET-e	V-MOS, LogL, 100V, ±15A, 35W, <60mΩ(6A)	17c	Nec	2SK1034, 2SK1306, 2SK1558
2SK737	MOS-N-FET-e	V-MOS, LogL, 100V, ±12A, 35W, <0,15Ω(6A)	7c	Nec	2SK1035, 2SK1305, 2SK1558
2SK738(Z)	MOS-N-FET-e	V-MOS, S-L, 30V, ±2A, 20W, <0,17Ω(1A)	30p	Nec	2SK973..74, 2SK1973
2SK739(Z)	MOS-N-FET-e	=2SK738: 60V, <0,25Ω(1A)	30p	Nec	2SK973..74, 2SK1973
2SK740	MOS-N-FET-e*	V-MOS, 150V, 10A, 50W, <0,15Ω(5A)	17p	Hit	BUZ31..32, 2SK459, 2SK890, 2SK925,++
2SK741	MOS-N-FET-e*	V-MOS, 250V, 7A, 50W, <0,55Ω(4A)	17p	Hit	2SK477, 2SK131920, 2SK1400
2SK742	MOS-N-FET-e	V-MOS, S-L, 50V, 5A, 30W, <0,22Ω	17c	Mat	BUK441-60, BUK541-60, 2SK499, 2SK1255+
2SK743	MOS-N-FET-e	V-MOS, S-L, 50V, 6A, 40W, <0,15Ω	17c	Mat	BUK542-50, BUZ72(A)F, 2SK1261, 2SK1556
2SK744	MOS-N-FET-e	V-MOS, S-L, 50V, 10A, 50W, <0,12Ω	17c	Mat	BUZ71(A)F, BUK442-50, 2SK1033, 2SK1093

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2SK745	MOS-N-FET-e	V-MOS, S-L, 50V, 20A, 100W, <0,055Ω	18p	Mat	2SK622, 2SK629, 2SK1267
2SK746	MOS-N-FET-e	V-MOS, S-L, 50V, 20A, 100W, <0,055Ω	16c(p)	Mat	2SK622, 2SK629, 2SK1267
2SK747	MOS-N-FET-e	V-MOS, S-L, 100V, 5A, 30W, <0,55Ω	17c	Mat	BUK442-100, BUK542-100, 2SK1260,++
2SK748	MOS-N-FET-e	V-MOS, S-L, 100V, 8A, 40W, <0,22Ω	17c	Mat	BUK443-100, BUK543-100, 2SK1261, ++
2SK749	MOS-N-FET-e	V-MOS, S-L, 100V, 10A, 50W, <0,18Ω	17c	Mat	BUK545-100, 2SK1230, 2SK1305, 2SK1430++
2SK750	MOS-N-FET-e	V-MOS, S-L, 100V, 20A, 100W, <0,08Ω	18p	Mat	2SK622, 2SK629, 2SK1267
2SK751	MOS-N-FET-e	V-MOS, S-L, 100V, 20A, 100W, <0,08Ω	16c(p)	Mat	2SK622, 2SK629, 2SK1267
2SK752	MOS-N-FET-e	V-MOS, S-L, 160V, 3A, 30W, <1Ω	17c	Mat	BUZ73(A)F, BUK444-200, 2SK1264
2SK753	MOS-N-FET-e	V-MOS, S-L, 160V, 5A, 40W, <0,5Ω	17c	Mat	BUZ73(A)F, BUK444-200, 2SK1265
2SK754	MOS-N-FET-e	V-MOS, S-L, 160V, 10A, 50W, <0,22Ω	17c	Mat	2SK525, 2SK1035
2SK755	MOS-N-FET-e	V-MOS, S-L, 200V, 5A, 40W, <0,5Ω(3A)	17c	Mat	BUZ73(A)F, BUK444-200, 2SK2010
2SK756	MOS-N-FET-e	V-MOS, S-L, 200V, 8A, 40W, <0,53Ω(3A)	17c	Mat	BUK445-200, BUK545-200, 2SK1476
2SK757	MOS-N-FET-e	V-MOS, S-L, 200V, 10A, 50W, <0,33Ω(5A)	17c	Mat	2SK526, 2SK1036, 2SK2212
2SK756	MOS-N-FET-e	V-MOS, S-L, 250V, 5A, 40W, <0,7Ω(3A)	17c	Mat	2SK2010, 2SK2345
2SK759	MOS-N-FET-e	V-MOS, S-L, 250V, 8A, 50W, <0,4Ω(5A)	17c	Mat	2SK1478, 2SK1568..69, 2SK1668
2SK760	MOS-N-FET-e	V-MOS, S-L, 250V, 15A, 100W, <0,22Ω	18p	Mat	2SK573, 2SK1135, 2SK1401
2SK761	MOS-N-FET-e	V-MOS, S-L, 250V, 15A, 100W, <0,22Ω	16c	Mat	2SK2012
2SK762	MOS-N-FET-e	V-MOS, S-L, 400V, 3A, 40W, <3Ω(2A)	17c	Mat	BUK445-450, 2SK1444, 2SK1862, 2SK2431 ++
2SK762A..765A	MOS-N-FET-e	=2SK762..765: 450V			—
2SK763	MOS-N-FET-e	V-MOS, S-L 400V, 5A, 50W, <1,4Ω(3A)	17c	Mat	BUK445-400, 2SK1251, 2SK1445, 2SK1992++
2SK764	MOS-N-FET-e	V-MOS, S-L 400V, 10A, 100W, <0,75Ω	18p	Mat	BUZ339, 2SK896, 2SK1468, 2SK1753,++
2SK765	MOS-N-FET-e	V-MOS, S-L, 400V, 10A, 100W, <0,75Ω	16c	Mat	2SK1206, 2SK1225, 2SK1328
2SK766	MOS-N-FET-e	V-MOS, 500V, 3A, 40W, <3,6Ω(2A)	17c	Mat	BUK445-500, 2SK1572, 2SK1767
2SK767	MOS-N-FET-e	V-MOS, 500V, 5A, 50W, <1,6Ω(3A)	17c	Mat	2SK1232, 2SK1351, 2SK1606, 2SK1627,++
2SK766	MOS-N-FET-e	V-MOS, 500V, 10A, 100W, <1Ω(5A)	18p	Mat	2SK724, 2SK696, 2SK1466, 2SK1753,++
2SK769	MOS-N-FET-e	=2SK766: Iso	16c	Mat	2SK1206, 2SK1523, 2SK1632
2SK770	MOS-N-FET-e	V-MOS, S-L, 600V, 2A, 40W, <5Ω(1A)	17c	Mat	BUK445-600, 2SK1758, 2SK1834, 2SK1953++
2SK771	N-FET	=2SK772: SMD	35f	Say	—
2SK772	N-FET	Analog-S, 40V, Idss=1,2..12mA, Up<2,5V	40e	Say	—
2SK773	MOS-N-FET-e	V-MOS, 500V, ±12A, 120W, <0,6Ω(8A)	18p	Nec	BUK637-500, 2SK644, 2SK896, 2SK1488
2SK774	MOS-N-FET-e	V-MOS, 500V, ±18A, 120W, <0,45Ω(9A)	18p	Nec	2SK670, 2SK1170, 2SK1516, 2SK1500,++
2SK775	MOS-N-FET-e	V-MOS, S-L, 450V, 2A, 50W, <3,5Ω(1A)	17p	Say	BUZ74, IRF820, IRF822, 2SK892
2SK776	MOS-N-FET-e	V-MOS, S-L, 450V, 5A, 60W, <1,6Ω(2A)	17p	Say	BUZ41A .42, 2SK1246, 2SK1440, 2SK1751 ++
2SK777	MOS-N-FET-e	V-MOS, S-L, 450V, 10A, 120W, <0,65Ω(5A)	18p	Say	BUZ339, 2SK644, 2SK663, 2SK1466,++
2SK776	MOS-N-FET-e	V-MOS, S-L, 250V, 0,5A, 10W, <9Ω(0,25A)	17p	Say	2SK296, 2SK1052
2SK779	GaAs-N-FET	SHF, 5V, 0,12A, 20..120mA, 12GHz	51(SGSD)	Hit	—
2SK760	GaAs-N-FET	SHF, 5V, 0,12A, Idss=20..120mA, 12GHz	51(SGSD)	Hit	—
2SK762	MOS-N-FET-e	V-MOS, S-L, 200V, 5A, 40W, <0,5Ω(3A)	30p	Mat	(2SK924, 2SK1391)
2SK763	MOS-N-FET-e	V-MOS, S-L, 500V, 12A, 125W, <0,57Ω)		Fjd	—
2SK764	MOS-N-FET-e	V-MOS, 450V, ±20A, 150W, <0,35Ω(10A)	18p	Nec	2SK668A, 2SK670, 2SK1517..18, 2SK1680,++
2SK766	MOS-N-FET-e	=2SK784: 500V, <0,4Ω(10A)	18p	Nec	2SK670, 2SK1500, 2SK1516, 2SK1680,++
2SK796	MOS-N-FET-e	V-MOS, 900V, ±3A, 60W, <7,5Ω(1,5A)	17p	Nec	BUK456-1000, 2SK792, 2SK1793
2SK767	MOS-N-FET-e	V-MOS, 900V, ±8A, 150W, <1,8Ω(4A)	18p	Nec	2SK1358, 2SK1502, 2SK1614, 2SK1892
2SK788	MOS-N-FET-e	V-MOS, S-L, 500V, 13A, 150W, <0,5Ω(7A)	18p	Tos	2SK560, 2SK725, 2SK1610, 2SK1745,++
2SK769	MOS-N-FET-e	V-MOS, S-L, 450V, 15A, 150W, <0,4Ω(7A)	18p	Tos	2SK559..560, 2SK725, 2SK1610, 2SK1745++
2SK79	N-FET	V-FET, NF, 120V, 0,2A, 0,75W	7c(9mm)	Son	—
2SK790	MOS-N-FET-e	V-MOS, S-L, 500V, 15A, 150W, <0,4Ω(7A)	18p	Tos	2SK680, 2SK725, 2SK1810, 2SK1745,++
2SK791	MOS-N-FET-e	V-MOS, 850V, 3A, 100W, <4,5Ω(1,5A)	17p	Tos	BUK456-1000, 2SK1466, 2SK1801, 2SK1638++
2SK792	MOS-N-FET-e	=2SK791: 900V	17p	Tos	BUK456-1000, 2SK1456, 2SK1601, 2SK1638++
2SK793	MOS-N-FET-e	V-MOS, 850V, 5A, 150W, <2,5Ω(3A)	18p	Tos	2SK727, 2SK1341, 2SK1649..50, 2SK1794,++
2SK794	MOS-N-FET-e	=2SK793: 900V	16p	Tos	2SK727, 2SK1341, 2SK1649..50, 2SK1794,++
2SK795	MOS-N-FET-e	=2SK770: 15W	≈30c	Mat	—
2SK796	MOS-N-FET-e	V-MOS, S-L, 800V, 3A, 90W, <5Ω(2A)	16c(p)	Mat	BUZ307, 2SK603, 2SK954, 2SK1339, ++
2SK796A	MOS-N-FET-e	=2SK796: 900V	16c(p)		2SK696, 2SK726, 2SK1339
2SK797	MOS-N-FET-e	V-MOS, LogL, 60V, ±40A, 150W, <18mΩ(20A)	18p	Nec	2SK1297, 2SK1514, 2SK1665
2SK798	MOS-N-FET-e	=2SK797: 100V, <31mΩ(20A)	18p	Nec	2SK1263, 2SK1304
2SK799	MOS-N-FET-e	=2SK773: 450V <0,5Ω(8A)	16p	Nec	BUK637-500, 2SK644, 2SK896, 2SK1488,++
2SK600	MOS-N-FET-e	=2SK774: 450V, <0,38Ω(8A)	16p	Nec	2SK668A, 2SK670, 2SK1170, 2SK1518,++
2SK601	MOS-N-FET-e	V-MOS, S-L, 30V, ±2A, 12W, <0,35Ω(1A)	30p	Nec	2SK973..974, 2SK1282
2SK802	MOS-N-FET-e	=2SK601: 15W	14j	Nec	2SK1263
2SK803	MOS-N-FET-e	V-MOS, S-L, 160V, 8A, 40W, <0,38Ω	17c	Mat	BUK445-200, BUK545-200, 2SK1478
2SK804	MOS-N-FET-e	V-MOS, S-L, 150V, 20A, 100W, <0,12Ω	16c	Mat	2SK622, 2SK1549, 2SK2008
2SK605	MOS-N-FET-e	V-MOS, S-L, 200V, 20A, 100W, <0,19Ω	16c	Mat	2SK622, 2SK1549, 2SK2008
2SK806	MOS-N-FET-e	V-MOS, S-L, 600V, 3A, 50W, <2,7Ω(2A)	17c	Mat	2SK1572, 2SK1767, 2SK2144
2SK607	MOS-N-FET-e	V-MOS, S-L, 600V, 5A, 100W, <1,7Ω(3A)	16c	Mat	BUK427-600, 2SK1176, 2SK1463, 2SK1859
2SK808	MOS-N-FET-e	V-MOS, S-L, 600V, 1A, 45W, <7Ω(0,7A)	17c	Mat	BUK444-800, 2SK1142, 2SK1611, 2SK1634++

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2SK808A	MOS-N-FET-e	=2SK808: 900V	17c		BUK446-1000, 2SK1174, 2SK1459, 2SK1994
2SK809	MOS-N-FET-e	V-MOS, S-L, 800V, 5A, 100W, <3Ω(3A)	16c	Mat	2SK1176, 2SK1463, 2SK1684, 2SK1859
2SK809A	MOS-N-FET-e	=2SK808: 900V	16c		2SK1176, 2SK1463, 2SK1684, 2SK1859
2SK810	MOS-N-FET-e	V-MOS, LogL, 100V, ±14A, 60W, <0,18Ω(8A)	17p	Nec	2SK1301, 2SK1559, 2SK1561
2SK811	MOS-N-FET-e	=2SK810: Iso, ±12A, 35W	17c	Nec	BUK545-100, 2SK1035, 2SK1305
2SK612	MOS-N-FET-e	V-MOS, LogL, 60V, ±27A, 60W, <85mΩ(15A)	17p	Nec	2SK1291, 2SK1296
2SK813	MOS-N-FET-e	=2SK810: Iso, ±21A, 35W	17c	Nec	2SK943, 2SK1214, 2SK1345..46
2SK614	MOS-N-FET-e	V-MOS, LogL, 30V, ±15A, 35W, <45mΩ(8A)	17c	Nec	2SK1034, 2SK1306, 2SK1558
2SK615	MOS-N-FET-e	V-MOS, LogL, 100V, ±21A, 35W, <85mΩ(15A)	17c	Nec	2SK1266, 2SK1307, 2SK1348..49
2SK617	MOS-N-FET-e	V-MOS, LogL, 50V, ±26A, 35W, <55mΩ(15A)	17c	Nec	2SK1262
2SK818	MOS-N-FET-e	V-MOS, S-Reg, 800V, 5A, 100W, <3Ω(3A)	18p	Mat	2SK727, 2SK1649..50, 2SK1760, 2SK1794, ++
2SK816A	MOS-N-FET-e	=2SK818: 900V	18p		2SK727, 2SK1849..50, 2SK1760, 2SK1794, ++
2SK619	MOS-N-FET-e	V-MOS, S-L, 500V, ±10A, 100W, <1Ω(5A)	18p	Nec	BUZ339, 2SK896, 2SK1488, 2SK1785, ++
2SK820	MOS-N-FET-e	V-MOS, 250V, ±16A, 60W, <0,23Ω(10A)	16c	Nec	2SK901, 2SK944, 2SK1641, 2SK1673, ++
2SK821	MOS-N-FET-e	V-MOS, 250V, ±20A, 150W, <0,23Ω(10A)	18p	Nec	2SK901, 2SK944, 2SK1641, 2SK1673, ++
2SK822	MOS-N-FET-e	V-MOS, 250V, ±22A, 90W, <0,15Ω(13A)	16c	Nec	2SK1670, (2SK944, 2SK1641, 2SK1673)
2SK823	MOS-N-FET-e	V-MOS, 250V, ±25A, 150W, <0,15Ω(13A)	18p	Nec	2SK902, 2SK1669, 2SK1671, 2SK1675
2SK824	MOS-N-FET-e	V-MOS, 450V, ±12A, 90W, <0,5Ω(7,5A)	16c	Nec	2SK1266..89, 2SK1524, 2SK1831
2SK825	MOS-N-FET-e	V-MOS, 450V, ±15A, 150W, <0,5Ω(7,5A)	18p	Nec	BUZ338, 2SK899, 2SK1573, 2SK1610, ++
2SK826	MOS-N-FET-e	V-MOS, 450V, ±15A, 95W, <0,38Ω(9A)	16c	Nec	2SK1268..89, 2SK1331, 2SK1524
2SK827	MOS-N-FET-e	V-MOS, 450V, ±18A, 150W, <0,38Ω(9A)	18p	Nec	BUZ338, 2SK899, 2SK1610, 2SK1680, ++
2SK828	MOS-N-FET-e	V-MOS, 500V, ±12A, 90W, <0,6Ω(7,5A)	16c	Nec	2SK1269, 2SK1331, 2SK1524
2SK829	MOS-N-FET-e	V-MOS, 500V, ±15A, 150W, <0,6Ω(7,5A)	18p	Nec	BUZ338, 2SK899, 2SK1610, 2SK1757, ++
2SK83	N-FET	FM/VHF, 25V, Idss>0,5mA, Up<2,5V	7f	Mat, Mic	BF410A, 2SK193, 2SK195, 2SK606, ++
2SK830	MOS-N-FET-e	V-MOS, 500V, ±15A, 95W, <0,45Ω(9A)	16c	Nec	2SK1269, 2SK1331, 2SK1524
2SK831	MOS-N-FET-e	V-MOS, 500V, ±18A, 150W, <0,45Ω(9A)	18p	Nec	BUZ338, 2SK899, 2SK1500, 2SK1610, ++
2SK832	MOS-N-FET-e	V-MOS, S-L, 900V, ±4A, 85W, <4Ω(3A)	16c	Nec	2SK809A, 2SK1463
2SK833	MOS-N-FET-e	V-MOS, S-L, 900V, ±5A, 150W, <4Ω(3A)	18p	Nec	2SK727, 2SK794, 2SK1341, 2SK1794, ++
2SK834	MOS-N-FET-e	V-MOS, S-L, 900V, ±8A, 100W, <1,6Ω(4A)	16c	Nec	2SK1465, 2SK1685
2SK839	MOS-N-FET	40V, 2A		Mat	—
2SK84	N-FET	NF/Uni, 55V, Idss=0,3..6,5mA, Up<5V	9e	Mat	BFS70, 2N3821, 2N4220, 2SK59, 2SK104, ++
2SK840	MOS-N-FET	40V, 2A		Mat	—
2SK841	MOS-N-FET	250V, 1A		Mat	—
2SK842	MOS-N-FET	400V, 0,5A		Mat	—
2SK843	MOS-N-FET-e	V-MOS, S-L, 60V, 10A, 40W, <0,1Ω(5A)	17c	Mit	BUK442-60, 2SK532, 2SK1093, 2SK1974, ++
2SK844	MOS-N-FET-e	V-MOS, S-L, 100V, 8A, 40W, <0,15Ω(4A)	17c	Mit	BUK443-100, BUZ72(A)F, 2SK1261
2SK845	MOS-N-FET-e	V-MOS, S-L, 450V, 5A, 40W, <1,3Ω(3A)	17c	Mit	2SK1231..32, 2SK1351, 2SK1808, 2SK1626++
2SK846	MOS-N-FET-e	V-MOS, S-L, 900V, 3A, 45W, <4Ω(1,5A)	17c	Mit	2SK1356, 2SK1460
2SK847	MOS-N-FET-e	=2SK846: 120W	=16c	Mit	2SK726, 2SK1339
2SK848	MOS-N-FET-e	V-MOS, SMD, 250V, 0,5A, <9Ω(0,25A)	39b	Say	—
2SK849	MOS-N-FET-e	V-MOS, 60V, 40A, 150W, <38mΩ(20A)	18p	Tos	2SK1124, 2SK1514, 2SK1665
2SK85	GaAs-N-FET	UHF, 10V, 0,1A, 8GHz	52(SGSD)	Nec	—
2SK850	MOS-N-FET-e	V-MOS, 100V, 35A, 150W, <60mΩ(20A)	18p	Tos	2SK1122, 2SK1263, 2SK1304
2SK851	MOS-N-FET-e	V-MOS, DC-DC, 200V, 30A, 150W, <65mΩ	18p	Tos	BUZ341, 2SK1492, 2SK1669, 2SK1671, ++
2SK852	N-FET	SMD, Uni, 50V, Idss=0,5..12mA, Up<1,5V	35f(2mm)	Nec	—
2SK853(A)	N-FET	SMD, Uni, 50V, Idss=0,5..12mA, Up<4,5V	35f(2mm)	Nec	—
2SK854	MOS-N-FET-e	V-MOS, 450V, ±5A, 50W, <1,4Ω(2,5A)	17p	Nec	BUZ41A..42, BUZ90, 2SK893, 2SK1246, ++
2SK855	MOS-N-FET-e	=2SK854: 500V, <1,5Ω(2,5A)	17p	Nec	BUZ41A..42, BUZ90, 2SK893, 2SK1246
2SK856	MOS-N-FET-e	V-MOS, DC-DC, 60V, 45A, 125W, <0,03Ω	17p	Tos	PRFZ42, 2SK1418, 2SK1542, 2SK1911
2SK857	MOS-N-FET-e	=2SK856:	18p	Tos	2SK1124, 2SK1297, 2SK1665, 2SK2096, ++
2SK858	MOS-N-FET-e	V-MOS, 600V, 2A, 40W, <4Ω(1A), 35/110ns	17p	Tos	BUZ60, 2SK1323..24
2SK859	MOS-N-FET-e	V-MOS, S-L, 500V, 9A, 125W, <0,8Ω(5A)	16c(p)	Fjd	BUZ330, BUZ353, 2SK557, 2SK724, ++
2SK863	MOS-N-FET-e	=2SK1257		Mat	→2SK1257
2SK864	MOS-N-FET-e	=2SK1256		Mat	→2SK1258
2SK665	MOS-N-FET-e	=2SK1282		Mat	→2SK1282
2SK866	MOS-N-FET-e	=2SK1283		Mat	→2SK1283
2SK887	MOS-N-FET-e	V-MOS, S-Reg, 400V, 15A, 120W, <0,45Ω	18p	Mat	BUK837-400, 2SK1610, 2SK1745, 2SK1757++-
2SK867A	MOS-N-FET-e	=2SK867: 450V	18p		BUK638-500, 2SK1610, 2SK1745, 2SK1757++
2SK866	MOS-N-FET-e	V-MOS, S-L, 400V, 20A, 130W, <0,35Ω	18p	Mat	2SK1169..70, 2SK1517..18, 2SK1497..98, ++
2SK868A	MOS-N-FET-e	=2SK868: 450V	18p		2SK1169..70, 2SK1517..18, 2SK1497..98, ++
2SK869	MOS-N-FET-e	V-MOS, S-L, 500V, 15A, 120W, <0,5Ω(8A)	18p	Mat	BUZ338, 2SK1610, 2SK1745, 2SK1757, ++
2SK87	N-FET	NF/Uni, 50V, Idss=0,3..6,5mA, Up<5V	2b	Hit	BFS70, 2N3821, 2N4220, 2SK59, 2SK104, ++
2SK870	MOS-N-FET-e	V-MOS, S-L, 500V, 20A, 130W, <0,4Ω(10A)	18p	Mat	2SK1170, 2SK1518, 2SK1498, 2SK1500, ++
2SK871	MOS-N-FET-e	V-MOS, S-L, 900V, ±4A, 120W, <5,5Ω(2A)	18p	Nec	2SK727, 2SK1461, 2SK1649..50, 2SK1760, ++
2SK872	MOS-N-FET-e	V-MOS, S-L, 900V, ±8A, 150W, <2,5Ω(3A)	18p	Nec	2SK1358, 2SK1614, 2SK1692, 2SK1795..96++
2SK873	MOS-N-FET-e	V-MOS, S-L, 450V, ±8A, 100W, <1,1Ω(4A)	18p	Nec	BUZ330..331, BUZ385, 2SK1468

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2SK874	MOS-N-FET-e	=2SK873: 500V, <1,2Ω(4A)	18p	Nec	BUZ330..331, BUZ385, 2SK1488
2SK875	MOS-N-FET-e	V-MOS, S-L, 450V, ±12A, 120W, <0,6Ω(6A)	18p	Nec	BUZ339, BUK637-500, 2SK724, 2SK896,++
2SK876	MOS-N-FET-e	=2SK875: 500V, <0,7Ω(6A)	18p	Nec	BUZ339, BUK637-500, 2SK724, 2SK896,++
2SK879	N-FET	SMD, NF-V, 50V, Idss=0,3..8,5mA, Up<5V	35f(2mm)	Tos	—
2SK880	N-FET	SMD, NF-V, 50V, Idss=0,8..14mA, Up<1,5V	35f(2mm)	Tos	—
2SK881	N-FET	SMD, FM/VHF, 18V, Idss=1..10mA, Up<4V	35c(2mm)	Tos	—
2SK882	MOS-N-FET-d*	SMD, VHF, 20V, Idss=3..14mA, Up<2,5V	35c(2mm)	Tos	—
2SK888	MOS-N-FET-e	V-MOS, 100V, 15A, 75W, <0,18Ω(6A)	17p	Tos	IRF640..643, 2SK919, 2SK922, 2SK1301,++
2SK889	MOS-N-FET-e	V-MOS, 100V, 27A, 125W, <85mΩ(15A)	17p	Tos	BUK456-100, 2SK1429
2SK890	MOS-N-FET-e	V-MOS, 200V, 10A, 75W, <0,4Ω(5A)	17p	Tos	BUZ31..32, 2SK925, 2SK1221, 2SK1393
2SK891	MOS-N-FET-e	V-MOS, 200V, 18A, 125W, <0,16Ω(10A)	17p	Tos	BUK456-200, BUZ30A, IRF640
2SK892	MOS-N-FET-e	V-MOS, 500V, 2,5A, 40W, <3Ω(1A)	17p	Tos	BUZ74, IRF820, IRF822, 2SK858,++
2SK893	MOS-N-FET-e	V-MOS, 500V, 5A, 75W, <1,5Ω(2,5A)	17p	Tos	BUZ41A..42, IRF830, IRF832, 2SK1246++
2SK894	MOS-N-FET-e	V-MOS, 500V, 6A, 125W, <0,85Ω(4A)	17p	Tos	BUK657-500, 2SK1496, 2SK1574
2SK895	MOS-N-FET-e	V-MOS, DC-DC, 450/20V, 12A, 125W, <0,6Ω	18p	Tos	BUZ339, 2SK899, 2SK1515..16, 2SK1610,++
2SK896	MOS-N-FET-e	=2SK895: 500V	18p	Tos	BUZ339, 2SK899, 2SK1516, 2SK1610,++
2SK897	MOS-N-FET-e	V-MOS, S-L, 550V, 4A, 40W, <1,5Ω(2A)	≈15c	Fjd	2SK1404, 2SK1837, 2SK2044, 2SK2118,++
2SK899	MOS-N-FET-e	V-MOS, S-L, 500V, 18A, 125W, <0,33Ω(6A)	18p	Fjd	2SK725, 2SK1170, 2SK1518, 2SK1880,++
2SK900	MOS-N-FET-e	V-MOS, S-Reg, 250V, 12A, 80W, <0,3Ω(6A)	17p	Fjd	2SK925, 2SK1221, 2SK1393
2SK901	MOS-N-FET-e	V-MOS, S-L, 250V, 20A, 125W, <0,15Ω	18p	Fjd	2SK623, 2SK944, 2SK1641, 2SK1873
2SK902	MOS-N-FET-e	V-MOS, S-L, 250V, 30A, 150W, <0,1Ω(15A)	18p	Fjd	2SK1669, 2SK1671, 2SK1675..76
2SK903	MOS-N-FET-e	V-MOS, S-L, 800V, 3A, 40W, <4Ω(1,5A)	≈15c	Fjd	2SK1356, 2SK1460, 2SK1995
2SK904	MOS-N-FET-e	=2SK903: 80W	17p	Fjd	BUK456-800, 2SK791..792, 2SK1600..01
2SK905	MOS-N-FET-e	V-MOS, S-L, 50V, 45A, 125W, <0,03Ω	18p	Fjd	BUZ347..348, 2SK857, 2SK1124, 2SK1514++
2SK906	MOS-N-FET-e	V-MOS, S-L, 100V, 32A, 125W, <0,06Ω	18p	Fjd	BUZ341, 2SK850, 2SK1303, 2SK1429
2SK917	MOS-N-FET-e	V-MOS, S-L, 100V, 5A, 40W, <0,5Ω	17p	Say	IRF510, IRF512, 2SK357, 2SK828
2SK918	MOS-N-FET-e	V-MOS, S-L, 100V, 10A, 50W, <0,3Ω	17p	Say	BUZ20, BUZ72, 2SK740, 2SK1427
2SK919	MOS-N-FET-e	V-MOS, S-L, 100V, 15A, 80W, <0,15Ω	17p	Say	BUZ21, IRF530, 2SK888, 2SK1559
2SK92	N-FET	NF/HF-V, 20V, Idss=0,02..1mA, Up<0,8V	7e	Nec	2SK93, 2SK103
2SK920	MOS-N-FET-e	V-MOS, S-L, 120V, 5A, 40W, <0,6Ω	17p	Say	IRF620, 2SK357
2SK921	MOS-N-FET-e	V-MOS, S-L, 120V, 10A, 50W, <0,35Ω	17p	Say	BUZ31, 2SK740
2SK922	MOS-N-FET-e	V-MOS, S-L, 120V, 15A, 80W, <0,2Ω	17p	Say	IRF641, IRF643
2SK923	MOS-N-FET-e	V-MOS, S-L, 250V, 3A, 40W, <1,4Ω	17p	Say	BUZ76, 2SK310..311
2SK924	MOS-N-FET-e	V-MOS, S-L, 250V, 5A, 50W, <0,8Ω	17p	Say	BUZ60, 2SK358, 2SK1391
2SK925	MOS-N-FET-e	V-MOS, S-L, 250V, 10A, 60W, <0,45Ω	17p	Say	2SK926, 2SK1221, 2SK1393
2SK926	MOS-N-FET-e	V-MOS, S-L, 250V, ±10A, 60W, <0,5Ω(5A)	17p	Nec	2SK925, 2SK1221, 2SK1393
2SK928	MOS-N-FET-e	V-MOS, 450V, ±5A, 35W, <1,4Ω(2,5A)	17c	Nec	2SK1231..32, 2SK1351, 2SK1608, 2SK1626++
2SK929	MOS-N-FET-e	=2SK928: 500V, <1,5Ω(2,5A)	17c	Nec	2SK1232, 2SK1351, 2SK1608, 2SK1627,++
2SK93	N-FET	NF-V, 20V, Idss=18..564μA	7e	Son	2SK92, 2SK103
2SK930	N-FET	=2SK433.	35f(2mm)	Mit	—
2SK931	N-FET	SMD, Uni, 30V, Idss=5..30mA, Up<2V	35f	Say	—
2SK932	N-FET	SMD, AM-Tuner, 15V, Idss=5..24mA, Up<1,4V	35f	Say	2SK931
2SK933	MOS-N-FET-e	V-MOS, S-L, 60V, ±15A, 35W	17c	Say	2SK1094, 2SK1286, 2SK1419
2SK934	MOS-N-FET-e	V-MOS, S-L, 250V, 6A, 40W, <0,52Ω(4A)	17c	Mit	2SK1478, 2SK1568..69, 2SK1668
2SK935	MOS-N-FET-e	=2SK934: 300V, <0,6Ω(4A)	17c	Mit	2SK1566, 2SK1569
2SK936	MOS-N-FET-e	V-MOS, 50V, 30A, 45W, <0,03Ω(15A)		Say	—
2SK937	N-FET	Uni, 40V, 0,1A, Idss=40..75mA, Up<5V	7e	Say	—
2SK94	N-FET	SMD, 50V, Idss=0,5..12mA, Up<1,5V	35f	Nec	2SK209, 2SK425
2SK940	MOS-N-FET-e*	V-MOS, LogL, 60V, 0,6A, 0,9W, <0,55Ω	7c(9mm)	Tos	2SK975, 2SK1274
2SK941	MOS-N-FET-e*	V-MOS, LogL, 100V, 0,6A, 0,9W, <1,3Ω	7c(9mm)	Tos	2SK1729, 2SK1736
2SK942	MOS-N-FET-e	V-MOS, LogL, 60V, 25A, 75W, <4mΩ(12A)	17p	Tos	BUK555-60, 2SK972, 2SK1115, 2SK1296,++
2SK943	MOS-N-FET-e	=2SK942: Iso, 40W	17c	Tos	2SK1345, 2SK1214, 2SK1348..49, 2SK1897++
2SK944	MOS-N-FET-e	V-MOS, DC-DC, 250V, 22A, 150W, <0,15Ω	18p	Tos	2SK901, 2SK1641, 2SK1673
2SK945	MOS-N-FET-e	V-MOS, DC-DC, 400V, 1A, 10W, <5Ω(0,5A)	30p	Tos	2SK535, 2SK579..580, 2SK1151
2SK946	MOS-N-FET-e	V-MOS, S-L, 900V, ±3A, 40W, <5,5Ω(2A)	17c	Nec	2SK1356, 2SK1460
2SK947	MOS-N-FET-e	V-MOS, S-Reg, 250V, 12A, 40W, <0,3Ω(6A)	≈15c	Fjd	2SK526, 2SK1036, 2SK1782
2SK948	MOS-N-FET-e	=2SK947: 10W	30p	Fjd	—
2SK949	MOS-N-FET-e	V-MOS, S-L, 500V, 6A, 40W, <1,2Ω(3,5A)	≈15c	Fjd	2SK1232, 2SK1351, 2SK1608, 2SK1627,++
2SK95	N-FET	NF/S, 150V, Idss<28mA, Up<9V		Shi	—
2SK950	MOS-N-FET-e	=2SK949: 80W	17p	Fjd	2SK893, 2SK1156, 2SK1246, 2SK1751,++
2SK951	MOS-N-FET-e	V-MOS, S-Reg, 800V, 2,5A, 40W, <7Ω(1A)	≈15c	Fjd	BUK446-800, 2SK1142, 2SK1611, 2SK1834++
2SK952	MOS-N-FET-e	V-MOS, S-Reg, 800V, 2,5A, 40W, <7Ω(1A)	17p	Fjd	BUZ60, 2SK1323..24, 2SK1456, 2SK1601,++
2SK953	MOS-N-FET-e	=2SK952: 80W	18p	Fjd	BUZ307..308, 2SK954, 2SK1339
2SK954	MOS-N-FET-e	V-MOS, S-L 800V, 3A, 100W, <4Ω(1,5A)	18p	Fjd	BUZ307, 2SK538, 2SK803, 2SK1339
2SK955	MOS-N-FET-e	V-MOS, S-L 800V, 5A, 125W, <2Ω(2,5A)	18p	Fjd	2SK534, 2SK604, 2SK695, 2SK727, 2SK793
2SK956	MOS-N-FET-e	V-MOS, S-L 800V, 9A, 150W, <1,5Ω(4A)	18p	Fjd	2SK1032, 2SK1796

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2SK957	MOS-N-FET-e	V-MOS, S-L 900V, 2A, 40W, <8,5Ω(1A)	≈15c	Fjd	2SK1143, 2SK1275, 2SK1459
2SK958	MOS-N-FET-e	=2SK957: 45W	17p	Fjd	2SK1199, 2SK1338, 2SK1324
2SK959	MOS-N-FET-e	=2SK957: 80W	18p	Fjd	2SK726, 2SK1339
2SK96	N-FET	=2SK95: 200V		Shi	—
2SK960	MOS-N-FET-e	V-MOS, S-L, 900V, 3A, 40W, <5Ω(1,5A)	≈15c	Fjd	2SK1356, 2SK1460, 2SK1995
2SK961	MOS-N-FET-e	=2SK960: 80W	17p	Fjd	2SK1601, 2SK1456, 2SK1638, 2SK1793,++
2SK962	MOS-N-FET-e	V-MOS, S-L, 900V, 8A, 150W, <2Ω(4A)	18p	Fjd	2SK1358, 2SK1614, 2SK1502, 2SK1795,++
2SK963	MOS-N-FET-e	=2SK758: 15W	≈30c	Mat	—
2SK968	N-FET	SMD, FM, 20V, Idss=0,6..12mA, Up<2,5V	35c	Say	2SK808
2SK969	GaAs-N-FET	SMD, HF, 16V, 20mA, Idss=1,2..12mA	35c	Say	—
2SK97	N-FET	Dual, 30V, Idss=0,9..14,3mA, Up<1,49V	6-DIP	Son	—
2SK970	MOS-N-FET-e*	V-MOS, LogL, 60V, 10A, 30W, <0,15Ω(5A)	17p	Hit	2SK1114, 2SK1300
2SK971	MOS-N-FET-e*	V-MOS, LogL, 60V, 15A, 40W, <65mΩ(8A)	17p	Hit	BUK552-60, 2SK942, 2SK1115..16, 2SK1347
2SK972	MOS-N-FET-e*	V-MOS, LogL, 60V, 25A, 50W, <40mΩ(15A)	17p	Hit	BUK555-60, 2SK942, 2SK1115, 2SK1296,++
2SK973(L,S)	MOS-N-FET-e*	V-MOS, LogL, 60V, 2A, 10W, <0,35Ω(1A)	30p	Hit	2SK1763
2SK974(L,S)	MOS-N-FET-e*	V-MOS, LogL, 60V, 3A, 20W, <0,18Ω(2A)	30p	Hit	2SK1113, 2SK1254, 2SK1282
2SK975	MOS-N-FET-e*	V-MOS, LogL, 60V, 1,5A, 0,9W, <0,4Ω(1A)	7c,b(9mm)	Hit	2SK1274, 2SK1733
2SK976	MOS-N-FET-e*	=2SK970: Iso, 20W	17c	Hit	2SK1093, 2SK1895, 2SK1878
2SK977	MOS-N-FET-e*	=2SK971: Iso, 25W	17c	Hit	2SK1094, 2SK1286, 2SK1306
2SK978	MOS-N-FET-e*	=2SK972: Iso, 30W	17c	Hit	2SK1290, 2SK1897, 2SK1951
2SK979	MOS-N-FET-e	V-MOS, 450V, 10A, 120W, 0,5Ω(5A)	18p	Sak	2SK724, 2SK896, 2SK1488, 2SK1752,++
2SK980	N-FET	SMD, Video-Frequ., 12V, 40mA, Idss>8mA	35f	Hit	—
2SK981(A)	MOS-N-FET-e	=2SK762(A): 15W	≈30c	Mat	—
2SK982	MOS-N-FET-e	S, 60V, 0,2A, 0,4W, <1Ω(50mA), 14/75ns	7c	Tos	BS170, BST170, 2SK422..423
2SK984	GaAs-N-FET	SHF, C..K-Band, 4V, Idss=0,5..2mA	52(SGSD)	Nec	—
2SK987	MOS-N-FET-e	V-MOS, S-L, 500V, 5A, 40W, <1,6Ω(3A)	17c	Mit	2SK1232, 2SK1351, 2SK1608, 2SK1627,++
2SK988	MOS-N-FET-e	V-MOS, S-L, 500V, 10A, 45W, <0,9Ω(5A)	17c	Mit	—
2SK989	MOS-N-FET-e	V-MOS, S-L, 500V, 10A, 120W, <0,9Ω(5A)	≈18p	Mit	2SK896, 2SK1488, 2SK1753, 2SK1785,++
2SK990	MOS-N-FET-e	V-MOS, S-L, 500V, 15A, 150W, <0,65Ω(8A)	≈18p	Mit	2SK999, 2SK1810, 2SK1678, 2SK1745,++
2SK991	MOS-N-FET-e*	V-MOS, LogL, 100V, ±4A, 35W, <0,5Ω(2A)	17p	Nec	2SK702, 2SK1474
2SK992	MOS-N-FET-e*	=2SK991: Iso, 30W	17c	Nec	BUK542-100, 2SK1260, 2SK1265
2SK993	MOS-N-FET-e*	V-MOS, LogL, 60V, ±8A, 35W, <0,25Ω(4A)	17p	Nec	BUK552-100
2SK994	MOS-N-FET-e*	=2SK993: Iso, ±7A, 30W	17c	Nec	BUK542-60, 2SK1033, 2SK1256, 2SK1344,++
2SK995	MOS-N-FET-e	FREDFET, S-L, 550V, 5A, 60W, <1,8Ω(3A)	16c	Mat	BUK627-600
2SK996	MOS-N-FET-e	V-MOS, S-L, 600V, 4A, 50W, <1,8Ω(2A)	17c	Mat	2SK1118, 2SK1404, 2SK1637, 2SK2044,++
2SK997	N-FET	C.-Mikrofon-V, 20V, 10mA, Idss>0,1mA	40a	Nec	—
2SK998	N-FET	UHF, 20V, 35mA, Idss>8mA, Up<2,2V	7d	Nec	—
2SM148	Triac	200V, 6A(Tc=75°), Igt/Ih<45/10mA	22m	Say	T2700B, TAG261-200, TAG266-200,++
2SM149	Triac	=2SM148: 400V	22m	Say	T2700D, TAG261-400, TAG266-400,++
2SM150	Triac	=2SM148: 600V	22m	Say	T2700M, TAG261-600, TAG266-600,++
2SM152	Triac	200V, 1A=, Igt<15mA	13j	Mat	TAG137.., TAG138..

2 ST 2ST

ТИП	СТРУКТУРА	ХАРАКТЕРИСТИКИ	КОРПУС	ПРОИЗВОДИТЕЛЬ	АНАЛОГ
2ST1396	Si-N+Di	=2SD1396	18j	Tho	→2SD1396
2ST1651FI	Si-N+Di	=2SD1651	18c	Tho	→2SD1651
2ST1877FI	Si-N+Di	=2SD1877	16c	Tho	→2SD1877
2ST1942	Si-N	=2SC1942	23a	Tho	→2SC1942
2ST2000	Si-N	=S2000	18j	Tho	→S2000
2ST2000FI	Si-N	=S2000AF	18c	Tho	→S2000AF
2ST3153	Si-N	=2SC3153: 1000V	18j	Tho	→2SC3153
2ST3412	Si-N	=2SC3412	23a	Tho	→2SC3412
2ST3460	Si-N	=2SC3460: 1500V	18j	Tho	BU508A, BU908, BU2508A
2ST3461	Si-N	=2SC3461: 1500V	18j	Tho	BU508A, BU908, BU2508A
2ST3485	Si-N	=2SC3485	18j	Tho	→2SC3485
2ST3485FI	Si-N	=2SC3485: Iso	18c	Tho	2SC3884A, 2SC3894
2ST3552	Si-N	=2SC3552: 1200V	18j	Tho	→2SC3552
2ST3842	Si-N	=2SC3842: 1200V	18j	Tho	→2SC3842
2ST3879FI	Si-N	=2SC3879: Iso, 1000V	16c	Tho	BUW11AF, 2SC4300, 2SC4427

2 T .... 2T..2Z

ТИП	СТРУКТУРА	ХАРАКТЕРИСТИКИ	КОРПУС	ПРОИЗВОДИТЕЛЬ	АНАЛОГ
2T	Si-N	=HT2 (Typ-Code/Stempel/marking)	35		→HT2
2T	Si-P	=KST4403 (Typ-Code/Stempel/marking)	35		→KST4403
2T	Si-P	=MMBT4403 (Typ-Code/Stempel/marking)	35		→MMBT4403
2T	Si-P	=SO4403 (Typ-Code/Stempel/marking)	35		→SO4403
2T	Si-P	=YTS4403 (Typ-Code/Stempel/marking)	35		→YTS4403
2T201	Ge-P	→2SA121..123		Son	—

ТИП	СТРУКТУРА	ХАРАКТЕРИСТИКИ	КОРПУС	ПРОИЗВОДИТЕЛЬ	АНАЛОГ
2T301	Ge-P	→2SB140		Son	—
2T302	Ge-P	→2SB141		Son	—
2T303	Ge-P	→2SB142..144		Son	—
2T304	Ge-P	→2SB145..146		Son	—
2T305	Ge-P	→2SB27..29		Son	—
2T306	Ge-P	→2SB30..31		Son	—
2T31	Ge-P	→2SB48..50		Son	—
2T32	Ge-P	→2SB51..52		Son	—
2T38	Ge-P	→2SB53		Son	—
2T73	Ge-N	→2SC73		Son	—
2T75	Ge-N	→2SC75		Son	—
2T76	Ge-N	→2SC76		Son	—
2T77	Ge-N	→2SC77		Son	—
2T76	Ge-N	→2SC78		Son	—
2U	Si-P	=KST63 (Typ-Code/Stempel/marking)	35		→KST63
2U	Si-P	=MMBTA63 (Typ-Code/Stempel/marking)	35		→MMBTA63
2V	Si-P	=KST64 (Typ-Code/Stempel/marking)	35		→KST64
2V	Si-P	=MMBTA64 (Typ-Code/Stempel/marking)	35		→MMBTA64
2V435	Si-P	→2N3726		Sgs	—
2W	Si-N	=2SC3704 (Typ-Code/Stempel/marking)	35		→2SC3704
2W	Si-N	=2SC3937 (Typ-Code/Stempel/marking)	35(2mm)		→2SC3937
2W	Si-P	=FMMT3905 (Typ-Code/Stempel/marking)	35		→FMMT3905
2W	Si-P	=MMBT8599 (Typ-Code/Stempel/marking)	35		→MMBT6599
2W01M..10M	Si-Br	50..1000V, 2A	6		B30..500C2200
2X	Si-N	=2SC3707 (Typ-Code/Stempel/marking)	35		→2SC3707
2X	Si-N	=2SC4410 (Typ-Code/Stempel/marking)	35(2mm)		→2SC4410
2X	Si-N	=KST4401 (Typ-Code/Stempel/marking)	35		→KST4401
2X	Si-N	=MMBT4401 (Typ-Code/Stempel/marking)	35		→MMBT4401
2X	Si-N	=SO4401 (Typ-Code/Stempel/marking)	35		→SO4401
2X	Si-N	=YTS4401 (Typ-Code/Stempel/marking)	35		→YTS4401
2Y4	Z-Di	=BZV49/C2V4 (Typ-Code/Stempel/marking)	39		→BZV49/C2V4
2Y7	Z-Di	=BZV49/C2V7 (Typ-Code/Stempel/marking)	39		→BZV49/C2V7
2YQ	Si-N	=2SC3757-Q (Typ-Code/Stempel/marking)	35		→2SC3757
2YQ	Si-N	=2SC3938-Q (Typ-Code/Stempel/marking)	35(2mm)		→2SC3938
2YQ	Si-N	=2SC4691-Q (Typ-Code/Stempel/marking)	35(1,6mm)		→2SC4691
2YQ	Si-N	=2SC4969-Q (Typ-Code/Stempel/marking)	≈35		→2SC4969
2YR	Si-N	=2SC3757-R (Typ-Code/Stempel/marking)	35		→2SC3757
2YR	Si-N	=2SC3938-R (Typ-Code/Stempel/marking)	35(2mm)		→2SC3938
2YR	Si-N	=2SC4691-R (Typ-Code/Stempel/marking)	35(1,6mm)		→2SC4691
2YR	Si-N	=2SC4969-R (Typ-Code/Stempel/marking)	≈35		→2SC4969
2YS	Si-N	=2SC3757-S (Typ-Code/Stempel/marking)	35		→2SC3757
2YS	Si-N	=2SC3938-S (Typ-Code/Stempel/marking)	35(2mm)		→29C3938
2YS	Si-N	=2SC4691-S (Typ-Code/Stempel/marking)	35(1,6mm)		→2SC4691
2Z	Si-N	=2SC4417 (Typ-Code/Stempel/marking)	35(2mm)		→2SC4417
2Z	Si-P	=MMBT6520 (Typ-Code/Stempel/marking)	35		→MMBT6520
2Z12..51	Z-Di	Z, TAZ, 12..51V, 10%, 600W(1ms)	31a	Tos	BZW70/.., BZX70/.., BZY93/..
3	C-Di	=HSU276,277 (Typ-Code/Stempel/marking)	71(1,7mm)		→HSU276, HSU277
3	C-Di	=HVU306(A) (Typ-Code/Stempel/marking)	71(1,7mm)		→HVU306(A)
3.0B	Z-Di	=HZF3.0BP (Typ-Code/Stempel/marking)	71(5mm)		→HZF3.0BP
3.0C	Z-Di	=HZF3.0CP (Typ-Code/Stempel/marking)	71(5mm)		→HZF3.0CP
3.3B	Z-Di	=HZF3.3BP (Typ-Code/Stempel/marking)	71(5mm)		→HZF3.3BP
3.3C	Z-Di	=HZF3.3CP (Typ-Code/Stempel/marking)	71(5mm)		→HZF3.3CP
3.6B	Z-Di	=HZF3.6BP (Typ-Code/Stempel/marking)	71(5mm)		→HZF3.6BP
3.6C	Z-Di	=HZF3.6CP (Typ-Code/Stempel/marking)	71(5mm)		→HZF3.6CP
3.9B	Z-Di	=HZF3.9BP (Typ-Code/Stempel/marking)	71(5mm)		→HZF3.9BP
3.9C	Z-Di	=HZF3.9CP (Typ-Code/Stempel/marking)	71(5mm)		→HZF3.9CP
30B	Z-Di	=HZF30BP (Typ-Code/Stempel/marking)	71(5mm)		→HZF30BP
30B	Z-Di	=HZF33BP (Typ-Code/Stempel/marking)	71(5mm)		→HZF33BP
30C	Z-Di	=HZF30CP (Typ-Code/Stempel/marking)	71(5mm)		→HZF30CP
30D1..D4	Si-Di	GI, Uni, 100..400V, 3A	31a	Inr	BY251..255, GP30A..M, 1N5400..06,++
30DF1..DF6	Si-Di	GI, S, 100..600V, 3A, 200..400ns	31a	Inr	BYW95A..C, BYW96D..E, RG3A..M,++
30DL1..DL4	Si-Di	GI, S, 100..400V, 2,7A, 800ns	31a	Inr	BYW95A..C, BYW96D..E, RG3A..M,++
30Y	Z-Di	=BZV49/C30 (Typ-Code/Stempel/marking)	39		→BZV49/C30
33C	Z-Di	=HZF33CP (Typ-Code/Stempel/marking)	71(5mm)		→HZF33CP
33Y	Z-Di	=BZV49/C33 (Typ-Code/Stempel/marking)	39		→BZV49/C33
359V	Si-Di	=1N5052: 900V	31a	Mic	BY227, BYX96, GP15M, 1N5399,++

ТИП	СТРУКТУРА	ХАРАКТЕРИСТИКИ	КОРПУС	ПРОИЗВОДИТЕЛЬ	АНАЛОГ
35SP-01..10	Si-Di	Dual, 50..1000V, 35A	=70	Gie	—
36B	Z-Di	=HZF 36BP (Typ-Code/Stempel/marking)	71 (5mm)		→HZF 36BP
36C	Z-Di	=HZF 36CP (Typ-Code/Stempel/marking)	71(5mm)		→HZF 36CP
36Y	Z-Di	=BZV 49/C36 (Typ-Code/Stempel/marking)	39		→BZV49/C36
37740	Si-P	=BC214	2a	Rca	→BC214
37741	Si-N	=2N5320	2a	Rca	→2N5320
36367	Si-N	=40361	2a	Rca	→40361
38388	Si-P	=40362	2a	Rca	→40362
364P	Si-Di	=1N5391: 900V	31a	Mic	BY227, BY255, BYW56, GP15M, ++
364V	Si-Di	=1N5391: 1100V	31a		BY227, BY255, BYX87, GH3E, ++
365A	Si-Di	GI, S, 50V, 1A, 300ns	31a	Mic	BY231/800, BY245/800, MR810..818, ++
365B	Si-Di	=385A: 100V	31a		BY231/800, BY245/800, MR811..818, ++
365C	Si-Di	=385A: 150V	31a		BY231/800, BY245/800, MR812..818, ++
365D	Si-Di	=365A: 200V	31a		BY231/800, BY245/800, MR812..818, ++
365F	Si-Di	=365A: 300V	31a		BY231/800, BY245/800, MR813..818, ++
365H	Si-Di	=385A: 400V	31a		BY231/800, BY245/800, MR814..818, ++
365K	Si-Di	=385A: 500V	31a		BY231/800, BY245/800, MR816..818, ++
365M	Si-Di	=385A: 800V	31a		BY231/800, BY245/800, MR816..818, ++
38647	Si-N	=2N5320	2a	Rca	→2N5320
386A	Si-Di	GI, S, 50V, 1A, 200ns	31a	Mic	BY201/2, BYT52A, BYV12, RGP10A, ++
366B	Si-Di	=386A: 100V	31a		BY201/2, BYT52B, BYV12, RGP10B, ++
366C	Si-Di	=386A: 150V	31a		BY201/2, BYT52D, BYV13, RGP10D, ++
386D	Si-Di	=386A: 200V	31a		BY201/2, BYT52D, BYV13, RGP10D, ++
386F	Si-Di	=386A 300V	31a		BY201/3, BYT52G, BYV13, RGP10G, ++
366H	Si-Di	=386A 400V	31a		BY201/4, BYT52G, BYV13, RGP10G, ++
366K	Si-Di	=386A: 500V	31a		BY201/5, BYT52J, BYV14, RGP10J, ++
366M	Si-Di	=386A: 800V	31a		BY201/6, BYT52J, BYV14, RGP10J, ++
367A	Si-Di	GI, S, 50V, 1A, 120ns	31a	Mic	BY201/2, BYT52A, BYV12, RGP10A, ++
367B	Si-Di	=367A: 100V	31a		BY201/2, BYT52B, BYV12, RGP10B, ++
367C	Si-Di	=387A: 150V	31a		BY201/2, BYT52D, BYV13, RGP10D, ++
367D	Si-Di	=386A: 200V	31a		BY201/2, BYT52D, BYV13, RGP10D, ++
367F	Si-Di	=387A: 300V	31a		BY201/3, BYT52G, BYV13, RGP10G, ++
367H	Si-Di	=387A: 400V	31a		BY201/4, BYT52G, BYV13, RGP10G, ++
367K	Si-Di	=387A: 500V	31a		BY201/5, BYT52J, BYV14, RGP10J, ++
367M	Si-Di	=387A: 800V	31a		BY201/6, BYT52J, BYV14, RGP10J, ++
386A	Si-Di	GI, S, 50V, 1A, 120ns	31a	Mic	BY201/2, BYT52A, BYV12, RGP10A, ++
368B	Si-Di	=386A: 100V	31a		BY201/2, BYT52B, BYV12, RGP10B, ++
368C	Si-Di	=386A: 150V	31a		BY201/2, BYT52D, BYV13, RGP10D, ++
368D	Si-Di	=388A: 200V	31a		BY201/2, BYT52D, BYV13, RGP10D, ++
386F	Si-Di	=388A: 300V	31a		BY201/3, BYT52G, BYV13, RGP10G, ++
368H	Si-Di	=388A: 400V	31a		BY201/4, BYT52G, BYV13, RGP10G, ++
368K	Si-Di	=388A: 500V	31a		BY201/5, BYT52J, BYV14, RGP10J, ++
368M	Si-Di	=386A: 800V	31a		BY201/6, BYT52J, BYV14, RGP10J, ++
398P	Si-Di	=1N5400: 700V	31a	Mic	BY254..255, BYW17/600, BYW65, ++
398V	Si-Di	=1N5400: 900V	31a		BY255, BYW17/1000, BYW86, ++
39Y	Z-Di	=BZV 49/C39 (Typ-Code/Stempel/marking)	39		→BZV49/C39
3A	Si-P	=BC 856AW (Typ-Code/Stempel/marking)	35(2mm)		→BC856W
3A	Si-N	=KST 24 (Typ-Code/Stempel/marking)	35		→KST24
3A	Si-St	=MA 30-A (Typ-Code/Stempel/marking)	71(1,7mm)		→HA30-A
3A	Si-N	=MMBTH 24 (Typ-Code/Stempel/marking)	35		→MMBTH24
3A(p,s)	Si-P	=BC 856A (Typ-Code/Stempel/marking)	35		→BC856
3A18	N-FET	=2N3619	7e		→2N3819
3AA11	Si-P-Darl+Di	3x Darl, -/100V, 2A, 2W, B>1000	8-SIP	Rhm	—
3AA12	Si-P-Darl+Di	3x Darl, -/120V, 6A, 2W, B>2000	8-SIP	Rhm	—
3AA13	Si-N-Darl+Di	3x Darl, -/80V, 4A, 2W, B>1000	8-SIP	Rhm	—
3AC11	Si-N-Darl+Di	3x Darl, -/100V, 2A, 2W, B>1000	8-SIP	Rhm	—
3AC12	Si-N-Darl+Di	3x Darl, -/120V, 6A, 2W, B>2000	8-SIP	Rhm	—
3AC13	Si-N-Darl+Di	3x Darl, -/80V, 4A, 2W, B>1000	8-SIP	Rhm	—
3AG	Si-P	=2SA1324-GR (Typ-Code/Stempel/marking)	35		→2SA1324
3AO	Si-P	=2SA1324-O (Typ-Code/Stempel/marking)	35		→2SA1324
3AR	Si-P	=BC 856AR (Typ-Code/Stempel/marking)	35		→BC856R
3As	Si-P	=BC 856AW (Typ-Code/Stempel/marking)	35(2mm)		→BC856W
3AY	Si-P	=2SA1324-Y (Typ-Code/Stempel/marking)	36		→2SA1324
3B	Si-P	=BC 856BW (Typ-Code/Stempel/marking)	36(2mm)		→BC856W
3B	Si-N	=FMMT 918 (Typ-Code/Stempel/marking)	35		→FMMT918
3B	Si-St	=MA 30-B (Typ-Code/Stempel/marking)	71(1,7mm)		→MA30-B

ТИП	СТРУКТУРА	ХАРАКТЕРИСТИКИ	КОРПУС	ПРОИЗВОДИТЕЛЬ	АНАЛОГ
3B	Si-N	=MMBT918 (Typ-Code/Stempel/marking)	35		→MMBT918
3B(p,s)	Si-P	=BC856B (Typ-Code/Stempel/marking)	35		→BC856
3BG	Si-P	=2SA1325-GR (Typ-Code/Stempel/marking)	35		→2SA1325
3BL	Si-P	=2SA1325-BL (Typ-Code/Stempel/marking)	35		→2SA1325
3BP	MOS-N-FET-d	=3SK139-P (Typ-Code/Stempel/marking)	44		→3SK139
3BQ	MOS-N-FET-d	=3SK139-Q (Typ-Code/Stempel/marking)	44		→3SK139
3BR	Si-P	=BC856BR (Typ-Code/Stempel/marking)	35		→BC856R
3Bs	Si-P	=BC856BW (Typ-Code/Stempel/marking)	35(2mm)		→BC856W
3C	Si-St	=MA30W-A (Typ-Code/Stempel/marking)	71(1,7mm)		→MA30W-A
3C	Si-P	=MMBT5179 (Typ-Code/Stempel/marking)	35		→MMBT5179
3C2	N-FET	=2N5245	7e		→2N5245
3C2P	N-FET	=2N5245	7f		→2N5245
3CO	Si-P	=2SA1326-O (Typ-Code/Stempel/marking)	35		→2SA1326
3CY	Si-P	=2SA1326-Y (Typ-Code/Stempel/marking)	35		→2SA1326
3D	Si-P	=BC856W (Typ-Code/Stempel/marking)	35(2mm)		→BC856W
3D	Si-St	=MA30W-B (Typ-Code/Stempel/marking)	71(1,7mm)		→MA30W-B
3D	Si-P	=MMBTH81 (Typ-Code/Stempel/marking)	35		→MMBTH81
3D(p)	Si-P	=BC856 (Typ-Code/Stempel/marking)	35		→BC856
3DO	MOS-N-FET-d	=3SK143-O (Typ-Code/Stempel/marking)	44		→3SK143
3DP	MOS-N-FET-d	=3SK143-P (Typ-Code/Stempel/marking)	44		→3SK143
3DQ	MOS-N-FET-d	=3SK143-Q (Typ-Code/Stempel/marking)	44		→3SK143
3E	Si-P	=BC857AW (Typ-Code/Stempel/marking)	35(2mm)		→BC857W
3E	Si-N	=FMMT-A42 (Typ-Code/Stempel/marking)	35		→FMMT-A42
3E	Si-N	=KST10 (Typ-Code/Stempel/marking)	35		→KST10
3E	Si-N	=MMBTH10 (Typ-Code/Stempel/marking)	35		→MMBTH10
3E(p,s)	Si-P	=BC857A (Typ-Code/Stempel/marking)	35		→BC857A
3EM	Si-N	=MMBTH10 (Typ-Code/Stempel/marking)	35		→MMBTH10
3EQ	MOS-N-FET-d	=3SK144-Q (Typ-Code/Stempel/marking)	44		→3SK144
3ER	MOS-N-FET-d	=3SK144-R (Typ-Code/Stempel/marking)	44		→3SK144
3ER	Si-P	=BC857AR (Typ-Code/Stempel/marking)	35		→BC857R
3Es	Si-P	=BC857AW (Typ-Code/Stempel/marking)	35(2mm)		→BC857W
3EZ3.9..200D	Z-Di	3,9..200V, ±..%, 3W	31e	Mot,Sie	BZT03/.., BZV16/.., BZX40/.., BZV48/..
3F	Si-P	=BC857BW (Typ-Code/Stempel/marking)	35(2mm)		→BC857W
3F	Si-N	=MMBT6543 (Typ-Code/Stempel/marking)	35		→MMBT6543
3F(p,s)	Si-P	=BC857B (Typ-Code/Stempel/marking)	35		→BC857
3FP	MOS-N-FET-d	=3SK169-P (Typ-Code/Stempel/marking)	44		→3SK169
3FQ	MOS-N-FET-d	=3SK169-Q (Typ-Code/Stempel/marking)	44		→3SK169
3FR	Si-P	=BC857BR (Typ-Code/Stempel/marking)	35		→BC857R
3Fs	Si-P	=BC857BW (Typ-Code/Stempel/marking)	35(2mm)		→BC857W
3G	Si-P	=BC857CW (Typ-Code/Stempel/marking)	35(2mm)		→BC857W
3G	Si-N	=MMBTH11 (Typ-Code/Stempel/marking)	35		→MMBTH11
3Gs	Si-P	=BC857CW (Typ-Code/Stempel/marking)	35(2mm)		→BC857W
3H	Si-P	=BC857W (Typ-Code/Stempel/marking)	35(2mm)		→BC857W
3H(p)	Si-P	=BC857 (Typ-Code/Stempel/marking)	35		→BC857
3J	Si-p	=BC858AW (Typ-Code/Stempel/marking)	35(2mm)		→BC856W
3J(p,s)	Si-p	=BC858A (Typ-Code/Stempel/marking)	35		→BC856
3Jp	Si-P	=BCV62A (Typ-Code/Stempel/marking)	44		→BCV62
3JR	Si-P	=BC858AR (Typ-Code/Stempel/marking)	35		→BC856R
3Js	Si-P	=BC858AW (Typ-Code/Stempel/marking)	35(2mm)		→BC856W
3Js	Si-P	=BCV62A (Typ-Code/Stempel/marking)	44		→BCV62
3K	Si-P	=BC856BW (Typ-Code/Stempel/marking)	35(2mm)		→BC856W
3K(p,s)	Si-P	=BC858B (Typ-Code/Stempel/marking)	35		→BC856
3Kp	Si-P	=BCV62B (Typ-Code/Stempel/marking)	44		→BCV62
3KR	Si-P	=BC858BR (Typ-Code/Stempel/marking)	35		→BC858R
3Ks	Si-P	=BC858BW (Typ-Code/Stempel/marking)	35(2mm)		→BC856W
3Ks	Si-P	=BCV62B (Typ-Code/Stempel/marking)	44		→BCV62
3L	Si-P	=BC856CW (Typ-Code/Stempel/marking)	35(2mm)		→BC856W
3L	Si-N	=MMBTH20 (Typ-Code/Stempel/marking)	35		→MMBTH20
3L(p,s)	Si-P	=BC858C (Typ-Code/Stempel/marking)	35		→BC856
3LP	N-FET	=2SK608-P (Typ-Code/Stempel/marking)	35		→2SK608
3Lp	Si-P	=BCV62C (Typ-Code/Stempel/marking)	44		→BCV62
3LQ	N-FET	=2SK608-Q (Typ-Code/Stempel/marking)	35		→2SK608
3LR	N-FET	=2SK608-R (Typ-Code/Stempel/marking)	35		→2SK608
3LR	Si-P	=BC858CR (Typ-Code/Stempel/marking)	35		→BC856R
3LS	N-FET	=2SK608-S (Typ-Code/Stempel/marking)	35		→2SK608
3Ls	Si-P	=BC858CW (Typ-Code/Stempel/marking)	35(2mm)		→BC856W

ТИП	СТРУКТУРА	ХАРАКТЕРИСТИКИ	КОРПУС	ПРОИЗВОДИТЕЛЬ	АНАЛОГ
3Ls	Si-P	=BCV62C (Typ-Code/Stempel/marking)	44		→BCV62
3M	Si-N	=2SC3829 (Typ-Code/Stempel/marking)	35		→2SC3829
3M	Si-N	=2SC4808 (Typ-Code/Stempel/marking)	35(1,6mm)		→2SC4808
3M	Si-N	=2SC4835 (Typ-Code/Stempel/marking)	35(2mm)		→2SC4835
3M	Si-P	=BC858W (Typ-Code/Stempel/marking)	35(2mm)		→BC858W
3M	Si-P	=FMMT5087R (Typ-Code/Stempel/marking)	35		→FMMT5087R
3M(p)	Si-P	=BC858 (Typ-Code/Stempel/marking)	35		→BC858
3Mp	Si-P	=BCV62 (Typ-Code/Stempel/marking)	44		→BCV62
3N		**3N...3SF**			
3N	MOS-N-FET-e	=2SK620 (Typ-Code/Stempel/marking)	35		→2SK620
3N	MOS-N-FET-e	=2SK664 (Typ-Code/Stempel/marking)	35(2mm)		→2SK664
3N100	Si-P	Chopper, 20V, 50mA, 0,3W	5	Tdy	—
3N101	Si-P	Chopper, 30V, 50mA, 0,3W	5	Tdy	—
3N102	Si-P	Chopper. 40V, 50mA, 0,3W	5	Tdy	—
3N103	Si-P	Chopper, 50V, 50mA, 0,3W	5	Tdy	—
3N104	Si-P	Chopper, 60V, 50mA, 0,3W	5	Tdy	—
3N105	Si-P	Chopper, 20V, 50mA, 0,3W	5	Tdy	—
3N108	Si-P	Chopper, 40V, 50mA, 0,3W	5	Tdy	—
3N107	Si-P	Chopper, 60V, 50mA, 0,3W	5	Tdy	—
3N108	Si-P	Chopper, 50V, 20mA, 0,3W	5	Tdy, Tix	—
3N109	Si-P	Chopper, 50V, 20mA, 0,3W	5	Tdy	—
3N110	Si-P	Chopper, 50V, 20mA, 0,3W	5	Tdy	—
3N111	Si-P	Chopper, 50V, 20mA, 0,3W	5	Tdy	—
3N112	Si-P	Chopper, 50V, 20mA, 0,2W		Tra	—
3N113	Si-P	Chopper, 50V, 20mA, 0,2W		Spr, Tdy, Tra	—
3N114	Si-P	Chopper, 30V, 20mA, 0,3W	5	Tdy	—
3N115	Si-P	Chopper, 30V, 20mA, 0,3W	5	Tdy	—
3N116	Si-P	Chopper, 30V, 20mA, 0,3W	5	Tdy	—
3N117	Si-P	Chopper, 50V, 20mA, 0,3W	5	Tdy	—
3N118	Si-P	Chopper, 50V, 20mA, 0,3W	5	Tdy	—
3N119	Si-P	Chopper, 50V, 20mA, 0,3W	5	Tdy	—
3N120	Si-N	Chopper, 30V, 10mA, 0,2W	5	Sld, Tdy	—
3N121	Si-N	Chopper, 30V, 10mA, 0,2W	5	Sld, Tdy	—
3N123	Si-P	Chopper, 30V, 20mA, 0,1W	5	Tdy	—
3N124	N-FET	Dual-Gate, 50V, Idss>0,2mA, Up<8V	5o	Mot	—
3N125	N-FET	=3N124: Idss>1,5mA, Up<14V	5o	Mot	—
3N126	N-FET	=3N124: Idss>3mA, Up<26V	5o	Mot	—
3N127	Si-N	Chopper, 30V, 10mA, 0,2W	5	Tra	—
3N128	MOS-N-FET-d	VHF-V/O, 20V, Idss>5mA, Up<8V	5m	MOT, Rca, ++	BFR29, 3N143, 3N152, 3N154
3N129	Si-P	Chopper, 20V, 20mA, 0,3W	5	Tdy	—
3N130	Si-P	Chopper, 30V, 20mA, 0,3W	5	Tdy	—
3N131	Si-P	Chopper, 40V, 20mA, 0,3W	5	Tdy	—
3N132	Si-P	Chopper, 50V, 20mA, 0,3W	5	Tdy	—
3N133	Si-P	Chopper, 60V, 20mA, 0,3W	5	Tdy	—
3N134	Si-P	Chopper, 20V, 20mA, 0,3W	5	Tdy	—
3N135	Si-P	Chopper, 40V, 20mA, 0,3W	5	Tdy	—
3N138	Si-P	Chopper, 60V, 20mA, 0,3W	5	Tdy	—
3N138	MOS-N-FET-d	S, Chopper, 45V, 0,05A	5m	Gie, Rca	—
3N139	MOS-N-FET-d	NF VHF, 42V, Idss>5mA	5m	Gie, Rca	—
3N140	MOS-N-FET-d	Dual-Gate, FM/VHF-V, 20V, Idss>5mA	5h	Gie, Mot, Rca	BF351, 3N201..206, 3N211..213
3N141	MOS-N-FET-d	Duel-Gate, FM/VHF-M, 20V, Idss>5mA	5h	Gie, Rca	BF351, 3N201..206, 3N211..213
3N142	MOS-N-FET-d	FM/VHF-VM/O, 20V, Idss>5mA, Up<8V	5m	Gie, Rca	BFR29, 3N143, 3N152, 3N154
3N143	MOS-N-FET-d	VHF-M/O, 20V, Idss>10mA, Up<8V	5m	Gie, Rca	BFR29, 3N142, 3N152, 3N154
3N145	MOS-P-FET-e	Uni, Chopper, 30V, Up<6V	5m	Gie	—
3N146	MOS-P-FET-e	Uni, Chopper, 30V, Up<6V	5m	Gie	—
3N147	MOS-P-FET-e	Dual, 20V, Idss>8mA, Up<12V	TO-76	Gie	—
3N148	MOS-P-FET-e	Dual, 20V, Idss>8mA, Up<12V	TO-76	Gie	—
3N149	MOS-P-FET-e	Uni, Chopper, 30V, Idss>16mA, Up<6V	5	Gie	—
3N150	MOS-P-FET-e	Uni, Chopper, 30V, Idss>16mA, Up<6V	5	Gie	—
3N151	MOS-P-FET-e	Dual, 30V, Idss<3mA, Up<6V	TO-77	Gie	—
3N152	MOS-N-FET-d	VHF, ra, 20V, Idss>10mA, Up<8V	5m	Gie, Rca	BFR29, 3N143, 3N154
3N153	MOS-N-FET-d	Chopper, 20V, 0,05A	5m	Gie, Rca	—
3N154	MOS-N-FET-d	VHF-V, 20V, Idss>10mA, Up<8V	5m	Gie, Rca	BFR29, 3N143, 3N152
3N155(A)	MOS-P-FET-e	Chopper, 35V, 0,03A, Up<3,2V	5n	Gie, Mot, Tix	BFW27, 3N160..161, 3N163..164
3N158(A)	MOS-P-FET-e	=3N155: Up<5V	5n	Gie, Mot, Tix	BFW27, 3N160..181, 3N183..164

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3N157(A)	MOS-P-FET-e	Chopper, 35..50V, 0,03A, Up<3,2V	5n	Gie, Mot, Tix	BFW27, 3N160..161, 3N163..164
3N158(A)	MOS-P-FET-e	=3N157: Up<5V	5n	Gie, Mot, Tix	BFW27, 3N160..161, 3N163..164
3N159	MOS-N-FET-d	Dual-Gate, 20V, Idss>5mA, Up<4V	5h	Gie, Rca	BF351, 3N201..206, 3N211..213
3N160	MOS-P-FET-e	Chopper, 25V, 0,125A, Up<5V	5	Gie, Isi, Tix	—
3N161	MOS-P-FET-e*	Chopper, 25V, 0,125A, Up<5V	5	Gie, Isi, Tix	—
3N162	MOS-P-FET-e	Chopper, 25V, 0,25A, Up<5V	5	Gie	—
3N163	MOS-P-FET-e	Chopper, 40V, 0,05A, Up<5V	5	Six, Tix, ++	—
3N164	MOS-P-FET-e	Chopper, 30V, 0,05A, Up<5V	5	Six, Tix, ++	—
3N165	MOS-P-FET-e	Dual, Chopper, 40V, 0,05A, Up<5V	TO-99	Gie, Isi, ++	—
3N166	MOS-P-FET-e	Dual, Chopper, 40V, 0,05A, Up<5V	TO-99	Gie, Isi, ++	—
3N167	MOS-P-FET-e	Chopper, 30V, 0,5A, Up<6V	5	Gie	—
3N168	MOS-P-FET-e	Chopper, 25V, 0,5A, Up<6V	5	Gie	—
3N169	MOS-N-FET-e	S, 35V, 0,03A, Up<1,5V	5n	Mot, Tix, ++	—
3N170	MOS-N-FET-e	=3N169: Up<2	5n	Mot, Tix, ++	—
3N171	MOS-N-FET-e	=3N169: Up<3	5n	Mot, Tix, ++	—
3N172	MOS-P-FET-e*	Chopper, 40V, 0,05A, Up<6V	5	Gie, Isi, Sol	—
3N173	MOS-P-FET-e*	=3N172: 30V	5	Gie, Isi, Sol	—
3N174	MOS-P-FET-e	Chopper, 30V, 0,02A, Up<6V	5	Gie, Tix	BFW27, 3N155..156, 3N163..164
3N175	MOS-N-FET-e	Chopper, 30V, 0,05A, Up<2V	5n	Gie	—
3N176	MOS-N-FET-e	Chopper, 25V, 0,05A, Up<2,5V	5n	Gie	—
3N177	MOS-N-FET-e	Chopper, 20V, 0,05A, Up<3,5V	5n	Gie	—
3N178	MOS-P-FET-e	Chopper, 75V, 0,02A, Up<5,5V	5	Gie	—
3N179	MOS-P-FET-e	Chopper, 60V, 0,02A, Up<6V	5	Gie	—
3N180	MOS-P-FET-e	Chopper, 40V, 0,02A, Up<6V	5	Gie	—
3N181	MOS-P-FET-e	Chopper, 30V, 0,1A, Up<4V	5	Gie	—
3N182	MOS-P-FET-e	Chopper, 30V, 0,1A, Up<5V	5	Gie	—
3N183	MOS-P-FET-e	Chopper, 25V, 0,1A, Up<6V	5	Gie	—
3N184	MOS-P-FET-e	Chopper, 35V, 0,05A, Up<3V	5	Gie	—
3N185	MOS-P-FET-e	Chopper, 30V, 0,05A, Up<3V	5	Gie	—
3N186	MOS-P-FET-e	Chopper, 25V, 0,05A, Up<3,5V	5	Gie	—
3N187	MOS-N-FET-d*	Dual-Gate, VHF, 20V, Idss>5mA, Up<4V	5h	Gie, Rca, Sol	BF351, 3N201..206, 3N211..213
3N188	MOS-P-FET-e*	Dual, Chopper, 40V, 0,05A, Up<5V	TO-99	Gie, Isi, Sol	—
3N189	MOS-P-FET-e*	Dual, Chopper, 40V, 0,05A, Up<5V	TO-99	Gie, Isi, Sol	—
3N190	MOS-P-FET-e	Dual, Chopper, 40V, 0,05A, Up<5V	TO-99	Gie, Isi, Sol	—
3N191	MOS-P-FET-e	Dual, Chopper, 40V, 0,05A, Up<5V	TO-99	Gie, Isi, Sol	—
3N192	MOS-N-FET-d	VHF, 30V, Idss<30mA, Up<4V	5m	Gie	—
3N193	MOS-N-FET-d	=3N192: Idss<20mA	5m	Gie	—
3N200	MOS-FET-N-d*	Dual-Gate, VHF/UHF, 20V, Idss>0,5mA	5h	Gie, Rca	3SK66, 3SK79, 3SK87, 3SK100
3N201	MOS-FET-N-d*	Dual-Gate, VHF-V, 30V, Idss>6mA, Up<5V	5h	Gie, Mot, Tix	BF351, 3N209..213
3N202	MOS-FET-N-d*	Dual-Gate, VHF-M, 30V, Idss>6mA, Up<5V	5h	Gie, Mot, Tix	BF351, 2N209..213
3N203(A)	MOS-FET-N-d*	Dual-Gate, TV-ZF, 30V, Idss>3mA, Up<5V	5h	Gie, Mot, Tix	BF351, 3N209..213
3N204	MOS-FET-N-d*	Dual-Gate, VHF/UHF, 30V, Idss>6mA	5h	Gie, Mot, Tix	3N209..210
3N205	MOS-FET-N-d*	Dual-Gate, VHF-M, 30V, Idss>6mA, Up<5V	5h	Gie, Mot, Tix	BF351, 3N209..213
3N206	MOS-FET-N-d*	Dual-Gate, TV-ZF, 30V, Idss>3mA, Up<5V	5h	Gie, Mot, Tix	BF351, 3N209..213
3N207	MOS-P-FET-e	Dual, 25V, 0,1A, Up<6V	TO-76	Gie, Tix	MEM551
3N208	MOS-P-FET-e*	Dual, 25V, 0,1A, Up<6V	TO-76	Gie, Tix	MEM550
3N209	MOS-N-FET-d*	Dual-Gate, UHF, 30V, Idss>5mA, Up<4V	5h	Mot	(BF900)
3N21	Ge-P	Tetrode, 60V, 0,1W		Syl	—
3N210	MOS-N-FET-d*	Dual-Gate, UHF, 30V, Idss>5mA, Up<4V		Mot	(BF900)
3N211	MOS-N-FET-d*	Dual-Gate, VHF-V, 35V, Idss>6mA, Up<5V	5h	Mot, Rca, Tix	BF351, 3N201..206
3N212	MOS-N-FET-d*	=3N211: VHF-M, Up<4V	5h	Mot, Rca, Tix	BF351, 3N201..206
3N213	MOS-N-FET-d*	=3N211: TV-ZF, 40V	5h	Mot, Rca, Tix	BF351, 3N201..206
3N214	MOS-N-FET-d	Uni, 20V, Idss>50mA, Up<6V	5m	Gie, Tix	—
3N215	MOS-N-FET-d	Uni, 20V, Idss>50mA, Up<6V	5m	Gie, Tix	—
3N216	MOS-N-FET-d	Uni, 20V, Idss>50mA, Up<6V	5m	Gie, Tix	—
3N217	MOS-N-FET-d	Uni, 20V, Idss>50mA, Up<6V	5m	Gie, Tix	—
3N218	MOS-P-FET-e	Chopper, 25V, 0,7A, Up<3,5V	5	Gie	—
3N22	Ge-N	Tetrode, 15V, 0,03W		Wes	—
3N223	MOS-N-FET-d	Dual-Gate, VHF, 40V, Idss<12mA, Up<2V	5h	Mot	BF352..353, BF963, 3SK81
3N224	MOS-N-FET-d	Dual-Gate, VHF, 40V, Idss<12mA, Up<2V		Mot	BF352..353, BF963, 3SK81
3N225(A)	MOS-N-FET-d	Dual-Gate, UHF, 25V, Idss>1mA, Up<4V	5h	Tix	3SK70, 3SK80
3N23	Ge-N	Tetrode, 30V, 5mA, 0,05W		Gie	—
3N242	MOS-N-FET-e	Chopper, 30V, 0,03A, Up<2V	5n	Gie	—
3N246	Si-Br	Gl-Br, 50V, 1A	33	Gie	B35C1000, etc.
3N247	Si-Br	=3N246: 100V	33		B70C1000, etc.
3N248	Si-Br	=3N246: 200V	33		B140C1000, etc.

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3N249	Si-Br	=3N246: 400V	33		B280C1000, etc.
3N25	Ge-P	Tetrode, 15V, 2mA, 0,025W		Tix	—
3N250	Si-Br	=3N246: 600V	33		B420C1000, etc.
3N251	Si-Br	=3N246: 600V	33		B560C1000, etc.
3N252	Si-Br	=3N246: 1000V	33		B700C1000, etc.
3N253	Si-Br	Gl-Br, 50V, 2A	33	Mot	B35C2000, etc.
3N254	Si-Br	=3N253: 100V	33		B70C2000, etc.
3N255	Si-Br	=3N253: 200V	33		B140C2000, etc.
3N256	Si-Br	=3N253: 400V	33		B280C2000, etc.
3N257	Si-Br	=3N253: 600V	33		B420C2000, etc.
3N258	Si-Br	=3N253: 600V	33		B560C2000, etc.
3N259	Si-Br	=3N253: 1000V	33		B700C2000, etc.
3N26	Si-N	Tetrode, 30V, 10mA, 0,125W		Tix	—
3N27	Si-N	Tetrode, 30V, 10mA, 0,125W		Tix	—
3N29	Ge-N	Tetrode, 7V, 20mA, 0,05W		Gen	—
3N30	Ge-N	Tetrode, 7V, 20mA, 0,05W		Gen	—
3N31	Ge-N	Tetrode, 7V, 20mA, 0,05W		Gen	—
3N32	Si-N	Tetrode, 30V, 10mA, 0,125W		Tix	—
3N33	Si-N	Tetrode, 30V, 10mA, 0,125W		Tix	—
3N34	Si-N	Tetrode, 30V, 20mA, 0,125W	5	Tix	—
3N35(A)	Si-N	Tetrode, 30V, 20mA, 0,125W	5	Tdy, Tix	—
3N36	Ge-N	Tetrode, 7V, 20mA 0,03W	5	Gen	—
3N37	Ge-N	Tetrode, 7V, 20mA 0,03W	5	Gen	—
3N39..44	IC	Reference amplifier			—
3N45	Ge-P	Tetrode, 60V, 12A, 75W		Sem	—
3N46	Ge-P	=3N45: 80V		Sem	—
3N47	Ge-P	=3N45: 40V		Sem	—
3N48	Ge-P	=3N45: 60V		Sem	—
3N49	Ge-P	=3N45: 15A, 94W	36	Gpd, Sem	—
3N50	Ge-P	=3N46: 15A, 94W	36	Gpd, Sem	—
3N51	Ge-P	=3N47: 15A, 94W	36	Gpd, Sem	—
3N52	Ge-P	=3N48: 15A, 94W	36	Gpd, Sem	—
3N56	Si-N	Tetrode, 18V, 0,03A, 0,15W	5	Tra	—
3N57	Si-N	Tetrode, 18V, 0,03A, 0,15W	5	Tra	—
3N58	Tetrode	40V, 0,1A(Ta=100°C)	5s	Gen	BR101, BRY20, BRY39, BRY21
3N59	Tetrode	=3N58	5s	Gen	BR101, BRY20, BRY39, BRY21
3N60	Tetrode	=3N58	5s	Gen	BR101, BRY20, BRY39, BRY21
3N62	Si-N	Chopper	5	Sld, Tdy	—
3N63	Si-N	Chopper	5	Sld, Tdy	—
3N64	Si-N	Chopper	5	Sld, Tdy	—
3N65	Si-N	Chopper	5	Sld, Tdy	—
3N66	Si-N	Chopper	5	Sld, Tdy	—
3N67	Si-N	Chopper	5	Sld, Tdy	—
3N68(A)	Si-N	Chopper	5	Sld, Tdy	—
3N69	Si-N	Chopper	5	Sld, Tdy	—
3N70	Si-N	Chopper	5	Sld, Tdy	—
3N71	Si-N	Chopper, 15V	5	Sld, Tdy	—
3N72	Si-N	Chopper, 15V	5	Sld, Tdy	—
3N73	Si-N	Chopper, 15V	5	Sld, Tdy	—
3N74	Si-N	Chopper, 50V	5	Sld, Tdy, Tix	—
3N75	Si-N	Chopper, 50V	5	Sld, Tdy, Tix	—
3N76	Si-N	Chopper, 50V	5	Sld, Tdy, Tix	—
3N77	Si-N	Chopper, 40V	5	Sld, Tdy, Tix	—
3N78	Si-N	Chopper, 40V	5	Sld, Tdy, Tix	—
3N79	Si-N	Chopper, 40V	5	Sld, Tdy, Tix	—
3N80	Tetrode	40V, 0,2A, Igt/Ih<1µA/6mA	5g	Gen	BRY20, BRY39, BRY21
3N81	Tetrode	65V, 0,2A	5g	Gen	BRY39, BRY21
3N82	Tetrode	=3N81: 100V	5g	Gen	BRY39, BRY21
3N83	Tetrode	70V, 0,05A, Igt/Ih<0,15/<4mA	5g	Gen	MAS32, BRY39, BRY21
3N64	Tetrode	40V, 0,175A, Igkt/Ih<0,01/<2mA	5g	Gen	BR101, BRY20, MAS32, BRY39, BRY21
3N85	Tetrode	=3N84: 100V	5g	Gen	BRY39, BRY21
3N86	Tetrode	=3N81	5g	Gen	→3N81
3N87	Si-N	Chopper, 20V, 10mA, 0,2W	5	Sld, Tdy	—
3N88	Si-N	Chopper, 20V, 10mA, 0,2W	5	Sld, Tdy	—
3N89	P-FET	Dual-Gate, 30V, Idss>0,5mA, Up<4V	5	Gie	—
3N90	Si-P	Chopper, 50V, 20mA, 0,3W	5	Tdy	—

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3N91	Si-P	Chopper, 50V, 20mA, 0,3W	5	Tdy	—
3N92	Si-P	Chopper, 50V, 20mA, 0,3W	5	Tdy	—
3N93	Si-P	Chopper, 50V, 20mA, 0,3W	5	Tdy	—
3N94	Si-P	Chopper, 50V, 20mA, 0,3W	5	Tdy	—
3N95	Si-P	Chopper, 50V, 20mA, 0,3W	5	Tdy	—
3N96	P-FET	Dual, 30V, Idss>0,5mA, Up<4V	TO-77	Six	—
3N97	P-FET	Dual, 30V, Idss>0,5mA, Up<4V	TO-77	Six	—
3N96	MOS-N-FET-d	Uni, 32V, Idss>3,5mA, Up<6V	5n	Rca	—
3N99	MOS-N-FET-d	Uni, 32V, Idss>5mA, Up<6V	5n	Rca	—
3O	Si-N	=2SC4497-O(Typ-Code/Stempel/marking)	35		→2SC4497
3O	MOS-N-FET-e	=2SK621 (Typ-Code/Stempel/marking)	35		→2SK621
3O	MOS-N-FET-e	=2SK665(Typ-Code/Stempel/marking)	35(2mm)		→2SK665
3P	Si-N	=FMMT 2222AR(Typ-Code/Stempel/marking)	35		→FMMT 2222AR
3P1M	50Hz-Thy	100V, 3A(Tc=87°C), Igt/Ih <5/=5mA	13e	Nec	X0609.., (TAG 621-.., TAG 622-.., ++)
3P1MH..3P6MH	50Hz-Thy	=3P1M..3P6M: Igt/Ih <0,2/1mA	13e		TAG 108-.., (TAG 623-.., TAG 628-.., ++)
3P2M	50Hz-Thy	=3PIM: 200V	13e		X0609.., (TAG 621-.., TAG 622-.., ++)
3P4J(Z)	50Hz-Thy	400V, 3A(Tc=103°C), Igt/Ih <0,1/<5mA	30e	Nec	—
3P4M	50Hz-Thy	=3PIM: 400V	13e		X0609.., (TAG 621-.., TAG 622-.., ++)
3P5M	50Hz-Thy	=3PIM: 500V	13e		X0609.., (TAG 621-.., TAG 622-.., ++)
3P6M	50Hz-Thy	=3PIM: 600V	13e		X0609.., (TAG 621-.., TAG 622-.., ++)
3R	Si-N	=2SC4497-R(Typ-Code/Stempel/marking)	35		→2SC4497
3R	Si-P	=MMBT 5771 (Typ-Code/Stempel/marking)	35		→MMBT 5771
3RP	GaAs-N-FET-d	=3SK184-P (Typ-Code/Stempel/marking)	44		→3SK184
3RQ	GaAs-N-FET-d	=3SK184-Q (Typ-Code/Stempel/marking)	44		→3SK184
3RR	GaAs-N-FET-d	=3SK184-R (Typ-Code/Stempel/marking)	44		→3SK184
3RS	GaAs-N-FET-d	=3SK184-S (Typ-Code/Stempel/marking)	44		→3SK184
3S	Si-N	=2SC3904 (Typ-Code/Stempel/marking)	35		→2SC3904
3S	Si-N	=2SC4805 (Typ-Code/Stempel/marking)	35(2mm)		→2SC4805
3S	Si-N	=MMBT 5551 (Typ-Code/Stempel/marking)	35		→MMBT 5551
3S4M	F-Thy	400V, 3A(Tc=70°C), Igt<30mA	13e	Nec	(TAG 650S-.., TAG 655S-.., CSF11-..)
3SF11	Tetrode	70V, 0,1A, Ih<1mA	5	Mat	—
3 SJ		**3SJ**			
3SJ11	MOS-P-FET-e	Chopper, 30V, 10mA, Up=3..6,5V, <1kΩ	5h	Nec	—
3SJ11A	MOS-P-FET-e	=3SJ11: 50mA, Up=1,5..3V, <500Ω	5h		—
3 SK		**3SK..3SZ**			
3SK100	MOS-N-FET-d	Dual-Gate, UHF, 15V, Idss>0,5mA, Up<3V	25g	Mat	3SK66, 3SK79, 3SK87
3SK101	MOS-N-FET-d*	Dual-Gate, VHF, 20V, Idss>3mA, Up<2,5V	25g	Tos	BF 961, 3SK37, 3SK45, 3SK61, 3SK77
3SK102	MOS-N-FET-d	Dual-Gate, UHF, 20V, Idss>3mA, Up<3,5V	25g	Tos	BF 900, BF 980
3SK103	MOS-N-FET-d	Dual-Gate, UHF, 15V, Idss<10mA, Up<1V	25g	Hit	BF 980
3SK104(V)	MOS-N-FET-d	Dual-Gate, UHF, 15V, Idss<20mA, Up<2V	25g	Hit	BF 980
3SK107	MOS-N-FET-d	Dual-Gate, FM/VHF, 20V, Idss>2,5mA, Up<3V	≈42	Say	BF 964, 3SK49
3SK108	MOS-N-FET-e	Dual-Gate, FM/VHF, 20V, Idss>3mA, Up<1,5V	≈42		—
3SK11	MOS-N-FET-d	Dual-Gate, 20V, Idss>0,5mA, Up<6V	5o	Hit	—
3SK112	GaAs-N-FET-e	Dual-Gate, UHF, 10V, Idss>20mA, Up<3,7V	25g	Tos	—
3SK113	GaAs-N-FET-d	Dual-Gate, UHF, 12V, Idss>10mA, Up<6V	25g	Tos	—
3SK114	MOS-N-FET-d	Dual-Gate, VHF, 15V, Idss>0mA, Up<1V	25g	Tos	3SK53
3SK115	MOS-N-FET-d	Dual-Gate, UHF, 15V, Idss>0mA, Up<1V	25g	Tos	3SK196
3SK116	MOS-N-FET-d	SMD, Duel-Gate, VHF, 20V, Idss>2,5mA, Up<3V	44l	Mat	BF 969, BF 991, BF 994, BF 996
3SK117	MOS-N-FET-d	SMD, Dual-Gate, UHF, 15V, Idss<6mA	44l	Mat	—
3SK118	MOS-N-FET-d	Dual-Gate, UHF, 15V, Idss>1mA, Up<1V	25g	Mat	—
3SK119	MOS-N-FET-d	Dual-Gate, VHF, 15V, Idss>0,8mA, Up<3V	25g	Mat	—
3SK12	MOS-N-FET-d	Dual-Gate, 20V, Idss>0,5mA, Up<6V	5o	Hit	—
3SK120	MOS-N-FET-d	Dual-Gate, VHF, 15V, Idss>2mA	25g	Mat	—
3SK121	GaAs-N-FETd*	Dual-Gate, UHF, 10V, Idss>20mA. Up<4V	25g	Tos	—
3SK122	MOS-N-FET-d	Dual-Gate, VHF-Tuner, 20V, Idss>7mA	25g	Nec	3SK74
3SK123	MOS-N-FET-d	Dual-Gate, UHF, 16V, Idss>0,01mA. Up<2V	25g	Nec	3SK68
3SK125	MOS-N-FET-d	Dual-Gate, VHF/UHF, 15V, Idss>1mA	25g	Mat	BF 960, BF 966
3SK126	MOS-N-FET-d	SMD, Dual-Gate, VHF, 15V, Idss>0mA, Up<1V	441	Tos	3SK195
3SK127	MOS-N-FET-d	SMD, Dual-Gate, UHF, 15V, Idss>0mA, Up<1V	441	Tos	3SK199
3SK126	MOS-N-FET-d	SMD, Dual-Gate, UHF, 15V, Idss>lmA	44(DSG2G1)	Mat	—
3SK129	GaAs-N-FET-d	Duel-Gate, 13V, Idss>8,5mA, Up<3,5V	25g	Mat	—
3SK13	MOS-N-FET-d	Dual-Gate, 20V, Idss>2mA, Up<8V	5o	Hit	—
3SK131	MOS-N-FET-d	SMD, Dual-Gate, VHF, 20V, Idss>7mA, Up<2V	441	Nec	—
3SK132(A)	MOS-N-FET-d	SMD, Dual-Gate, UHF, 20V, Idss>0,5mA, Up<2V	44l	Nec	—

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3SK133(A)	MOS-N-FET-d	SMD, Dual-Gate, UHF, 20V, Idss>10μA, Up<2V	44l	Nec	—
3SK134	MOS-N-FET-d	SMD, Dual-Gate, UHF-Tuner, 15V	44l	Nec	—
3SK135(A)	MOS-N-FET-d	SMD, Dual-Gate, UHF-Tuner, 15V, Idss>10μA	44l	Nec	3SK133
3SK136	MOS-N-FET-d	SMD, Dual-Gate, VHF, 20V, Idss>5mA, Up<3V	44l	Hit	BF993
3SK137	MOS-N-FET-d	SMD, Dual-Gate, UHF, 15V, Idss<20mA, Up<2V	44l	Hit	—
3SK137V	MOS-N-FET-d	=3SK137: VHF	44l		—
3SK136	MOS-N-FET-d	SMD, Dual-Gate, UHF, 15V, Idss<10mA, Up<1V	44l	Hit	—
3SK139	MOS-N-FET-d	=3SK125: SMD	44l	Mat	—
3SK14	MOS-N-FET-d	Chopper, 20V, 10mA, Idss=1mA, Up<5V	5n	Nec	—
3SK140	GaAs-N-FET-d	SMD, Dual-Gata, UHF-TV-Tuner	44l	Tos	—
3SK141	GaAs-N-FET-d	=3SK129: SMD	44l	Mat	—
3SK142	MOS-N-FET-d	Dual-Gate, UHF, 15V, Idss>0,5mA	25g	Mat	3SK79, 3SK87, 3SK100
3SK143	MOS-N-FET-d	=3SK142: SMD, Idss>0,2mA	44l	Mat	—
3SK144	MOS-N-FET-d	SMD, Dual-Gate, VHF, 15V, Idss>0,8mA	44l	Mat	—
3SK145	MOS-N-FET-d	Dual-Gate, UHF, 13,5V, Idss=0..6mA	25g	Tos	—
3SK146	MOS-N-FET-d	=3SK145: SMD	44l	Tos	—
3SK15(A)	MOS-N-FET-d	Dual-Gate, 25V, Idss<10mA, Up<9V	5o	Mit	—
3SK150	MOS-N-FET-d	Dual-Gate, VHF/UHF, 15V, Idss>3mA	25g	Tos	BF980
3SK151	MOS-N-FET-d	=3SK150: SMD	44l	Tos	—
3SK152	MOS-N-FET-d	Dual-Gate, VHF/UHF, 13,5V, Idss=0..6V	25g	Tos	—
3SK153	MOS-N-FET-d	=3SK152: SMD	44l	Tos	—
3SK154	MOS-N-FET-d	=3SK96: SMD	44l	Hit	—
3SK156	MOS-N-FET-d	Dual-Gate, VHF, 12V, Idss=0..12mA	25g	Hit	—
3SK159	MOS-N-FET-d	Dual-Gate, VHF/UHF, 13,5V, Idss=06mA	25g	Tos	—
3SK16	MOS-N-FET-d	Dual-Gate, 25V, Idss<10mA, Up<9V	5o	Mit	—
3SK160	MOS-N-FET-d	=3SK159: SMD	44l	Tos	—
3SK162	MOS-N-FET-d	SMD, Dual-Gate, VHF, 12V, Idss=0..12mA	44l	Hit	—
3SK163	MOS-N-FET	SMD, S, 15V, 100mA, Uon<5,5V	44(SubDSG)	Son	—
3SK164	GaAs-N-FET-d	SMD, Dual-Gate, UHF, 12V, Idss>10mA	44l	Son	—
3SK165	GaAs-N-FET-d	SMD, Dual-Gate, UHF, 8V, Idss>20mA	44l	Son	—
3SK166	GaAs-N-FET-d	SMD, Dual-Gate, UHF, 8V, Idss>20mA	44l	Son	—
3SK167	GaAs-N-FET-d	Dual-Gate, UHF-V/M, 12V, Idss>10mA	441	Say	—
3SK168	GaAs-N-FET-d	Dual-Gate, UHF-Tuner, 12V, Idss>10mA	42	Say	—
3SK169	MOS-N-FET-d	SMD, Dual-Gate, VHF, 15V, Idss>1,5mA	44l	Mat	—
3SK17	MOS-N-FET-d	Dual-Gate, 25V, Idss<10mA, Up<9V	5o	Mit	—
3SK171	GaAs-N-FET-d	=3SK113: SMD	44l	Hit	—
3SK173	MOS-N-FET-d	Dual-Gate, CATV, 18V, Idss=0,5..10mA	25g	Nec	—
3SK174	GaAs-N-FET-d	Dual-Gate, UHF, 13V, Idss=5..40mA	25g	Nec	—
3SK176(A)	MOS-N-FET-d	=3SK173: SMD	44l	Nec	—
3SK177	GaAs-N-FET-d	=3SK174: SMD	44l	Nec	—
3SK179	MOS-N-FET-d	SMD, Dual-Gate, VHF, 20V, Idss>7mA	44l	Nec	—
3SK16	MOS-N-FET-d	Duel-Gete, 15V, Idss<5mA, Up<6V	5o	Mit	—
3SK180	MOS-N-FET-d	SMD, Dual-Gate, FM/VHF, 15V, Idss>2,5mA	44l	Say	—
3SK181	MOS-N-FET-e	SMD, Dual-Gate, FM/VHF, 15V	44l	Say	—
3SK182	MOS-N-FET-d	=3SK80: SMD	44l	Hit	—
3SK183	GaAs-N-FET-d	Dual-Gate, UHF, 13V, Idss>8,5mA, Up<6V	25g	Mat	—
3SK184	GaAs-N-FET-d	=3SK183: SMD	44l	Mat	—
3SK186	MOS-N-FET-d	SMD, Dual-Gate, UHF, 12V, Idss=04V	44l	Hit	—
3SK187	GaAs-FET	SMD, Dual-Gate, 20V, Idss=8,5..130mA	44l	Mat	—
3SK186	MOS-N-FET-d	=3SK85: SMD	44l	Hit	—
3SK189	GaAs-N-FET-d	SMD, Dual-Gate, UHF, 13V, Idss>8,5mA	44l	Say	—
3SK19	MOS-N-FET-d	Dual-Gate, VHF, 15V, Idss<5mA, Up<6V	5o	Mit	—
3SK190	GaAs-N-FET-d	=3SK189:	42	Say	—
3SK191	GaAs-N-FET-d	SMD, Dual-Gate, UHF, 12V, Idss>10mA	44l	Hit	—
3SK192	MOS-N-FET-d	SMD, Dual-Gate, VHF, 15V, Idss>1mA	44l	Mat	3SK193
3SK193	MOS-N-FET-d	SMD, Dual-Gate, VHF, 15V, Idss>1mA	44l	Mat	3SK192
3SK194	MOS-N-FET-d	SMD, Dual-Gate, VHF/UHF-Tuner, 15V, 35mA	44l	Hit	—
3SK195	MOS-N-FET-d	SMD, Dual-Gate, VHF, 13,5V, Idss>0mA	44l	Tos	3SK126
3SK196	MOS-N-FET-d	SMD, Dual-Gate, VHF/UHF-Tuner, 12V, 35mA	44l	Hit	—
3SK197	MOS-N-FET-d	SMD, Dual-Gate, VHF-TV-Tuner, 12V, 35mA	44l	Hit	—
3SK198	MOS-N-FET-d	Dual-Gate, UHF, 13,5V, Idss>0mA	25g	Tos	3SK115
3SK199	MOS-N-FET-d	=3SK196: SMD	44l	Tos	3SK127
3SK20	MOS-N-FET-d	Dual-Gate, Uni, 20V, Idss>0,5mA, Up<3,5V	5o	Hit	3SK66, 3SK79, 3SK87, 3SK100
3SK200	MOS-N-FET-d	SMD, Dual-Gate, UHF, 15V, Idss>4mA	44l	Mat	—
3SK201	MOS-N-FET-d	SMD, Dual-Gate, UHF, 13V, Idss>8,5mA	44l	Mat	—
3SK202	MOS-N-FET-d	Dual-Gate, VHF, 15V, Idss>0,8mA, Up<3V	25g	Mat	—

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3SK203	GaAs-N-FET-d	Dual-Gate, UHF, 10V, Idss=8..60mA	25g	Nec	—
3SK204	GaAs-N-FET-d	=3SK203: SMD	44l	Nec	—
3SK205	GaAs-N-FET-d	Dual-Gate, UHF, 10V, Idss=10..60mA	25g	Nec	—
3SK206	GaAs-N-FET-d	=3SK205: SMD	44l	Nec	—
3SK207	MOS-N-FET-d	SMD, Dual-Gate, UHF, 13,5V, Idss>0V	44l	Tos	—
3SK21	MOS-N-FET-d	Dual-Gate, Chopper, 20V, Idss>3mA	5o	Hit	—
3SK212	GaAs-N-FET-d	Dual-Gate, UHF, TV-Tuner, 10V, 15mA	44l	Rhm	—
3SK215	GaAs-N-FET-d	SMD, TV-UHF, 12V, 1mA, Idss>6mA	44	Tos	—
3SK216	GaAs-N-FET-d	SMD, TV-UHF, 12V, 1mA, Idss>4mA	44	Tos	—
3SK217	MOS-N-FET-d	=3SK186:	44l	Hit	—
3SK219	MOS-N-FET-d	SMD, Dual-Gate, VHF, 15V, 30mA	44l	Mat	—
3SK22	N-FET	Dual-Gate, FM/VHF, 18V, Idss>3mA, Up<5V	5(DSG1G2)	Tos	—
3SK220	MOS-N-FET-d	SMD, Dual-Gate, VHF/UHF, 15V, 30mA	44l	Mat	—
3SK222	MOS-N-FET-d	SMD, Dual-Gate, VHF, 18V, 25mA	44l	Nec	—
3SK223	MOS-N-FET-d	SMD, Dual-Gate, CATV, 18V, 25mA	44l	Nec	—
3SK224	MOS-N-FET-d	SMD, Dual-Gate, CATV, 18V, 25mA	44l	Nec	—
3SK225	MOS-N-FET-d	SMD, Dual-Gate, FM..UHF, 13,5V, Idss>0V	44l	Tos	—
3SK226	MOS-N-FET-d	SMD, Dual-Gate, FM/VHF, 13,5V, Idss>0V	44l	Tos	—
3SK227	MOS-N-FET-d	SMD, Dual-Gate, UHF, 15V, 30mA	44l	Mat	—
3SK228(A)	GaAs-N-FET-d	SMD, Dual-Gate, UHF-TV-Tuner, 12V, 50mA	44l	Hit	—
3SK229	GaAs-N-FET-d	SMD, Dual-Gate, UHF-TV-Tuner, 12V, 60mA	44l	Hit	—
3SK23	N-FET	Dual-Gate, FM/VHF, 15V, Idss>6mA, Up>1,8V	5(DSG1G2)	Tos	—
3SK230	MOS-N-FET-d	SMD, Dual-Gate, CATV, 18V, 25mA	44l	Nec	—
3SK231	MOS-N-FET-d	SMD, Dual-Gate, UHF, 18V, 25mA	44l	Nec	—
3SK232	MOS-N-FET-d	SMD, Dual-Gate, UHF, 12,5V, Idss<0,1mA	44l	Tos	—
3SK233	MOS-N-FET-d	SMD, Dual-Gate, UHF-TV-Tuner, 12V, 35mA	44l	Hit	—
3SK234	MOS-N-FET-d	SMD, Dual-Gate, VHF-TV-Tuner, 12V, 35mA	44l	Hit	—
3SK235	MOS-N-FET-d	SMD, Dual-Gate, VHF/UHF-Tuner, 12V, 35mA	44l	Hit	—
3SK236	MOS-N-FET-d	=3SK234:	44l(2mm)	Hit	—
3SK237	MOS-N-FET-d	=3SK235:	44l(2mm)	Hit	—
3SK236	MOS-N-FET-d	=3SK233:	44l(2mm)	Hit	—
3SK239A	MOS-N-FET-d	=3SK228A:	44l(2mm)	Hit	—
3SK24	MOS-N-FET-d	→3SK39	5h	Mat	—
3SK240	GaAs-N-FET-d	SMD, Dual-Gate, UHF, 9V, Idss=8..20mA	44l	Tos	—
3SK241	GaAs-N-FET-d	SMD, Dual-Gate, VHF/UHF, 13V, 50mA	44l	Mat	—
3SK242	MOS-N-FET-d	SMD, Dual-Gate, VHF-Tuner, 20V, 25mA	44l(2mm)	Nec	—
3SK243	MOS-N-FET-d	SMD, Dual-Gate, CATV-Tuner, 18V, 25mA	44l(2mm)	Nec	—
3SK244	MOS-N-FET-d	SMD, Dual-Gate, UHF-Tuner, 18V, 25mA	44l(2mm)	Nec	—
3SK245	MOS-N-FET-d	SMD, Dual-Gate, UHF-Tuner, 18V, 25mA	44l(2mm)	Nec	—
3SK246	MOS-N-FET-d	SMD, Dual-Gate, FM/VHF, 18V, 25mA	44l(2mm)	Nec	—
3SK247	MOS-N-FET-d	SMD, Dual-Gate, VHF, 15V, Idss=0..10mA	44l	Mat	—
3SK248	MOS-N-FET-e	SMD, Dual-Gate, 10V, 100mA, Up<1,5V	44l	Say	—
3SK249	MOS-N-FET-d	=3SK232:	44l(2mm)	Tos	—
3SK25	MOS-N-FET-d	→3SK39	5h	Mat	—
3SK250	GaAs-N-FET-d	SMD, Duel-Gate, UHF-TV-Tuner, 6V	44l	Tos	—
3SK252	MOS-N-FET-d	SMD, Dual-Gate, CATV-Tuner, 18V, 25mA	44l	Nec	—
3SK253	MOS-N-FET-d	SMD, Dual-Gate, UHF-Tuner, 18V, 25mA	44l	Nec	—
3SK255	MOS-N-FET-d	=3SK253:	44l(2mm)	Nec	—
3SK255	MOS-N-FET-d	=3SK226:	44l(2mm)	Tos	—
3SK256	MOS-N-FET-d	=3SK207:	44l(2mm)	Tos	—
3SK257	MOS-N-FET-d	=3SK225:	44l(2mm)	Tos	—
3SK259	MOS-N-FET-d	=3SK152: SMD	44l(2mm)	Tos	—
3SK260	MOS-N-FET-d	=3SK150: SMD	44l(2mm)	Tos	—
3SK263	MOS-N-FET-d	SMD, Dual-Gate, 15V, 30mA, Idss>2,5mA	44l	Say	—
3SK264	MOS-N-FET-d	SMD, Dual-Gate, 15V, 30mA, Idss>5mA	44l	Say	—
3SK265	MOS-N-FET-d	SMD, Dual-Gate, 15V, 30mA, Idss>5mA	44l	Say	—
3SK266	MOS-N-FET-d	SMD, Dual-Gate, 13,5V, 30mA, Idss>2,5mA	44l	Say	—
3SK268	MOS-N-FET-d	=3SK219:	44l(2mm)	Mat	—
3SK269	MOS-N-FET-d	=39K200:	44l(2mm)	Mat	—
3SK270	MOS-N-FET-d	=3SK220:	44l(2mm)	Mat	—
3SK271	MOS-N-FET-d	=3SK227:	44l(2mm)	Mat	—
3SK272	GaAs-N-FET-d	=3SK241:	44l(2mm)	Mat	—
3SK273	GaAs-N-FET-d	SMD, Dual-Gate, VHF/UHF, 13V, 50mA	44l	Mat	—
3SK274	GaAs-N-FET-d	=3SK240:	44l(2mm)	Tos	—
3SK275	GaAs-N-FET-d	=3SK250:	44l(2mm)	Tos	—
3SK276	MOS-N-FET-d	SMD, Dual-Gate, VHF/UHF, 12V, 25mA	44l	Hit	—

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3SK28	N-FET	Dual-Gate, FM/VHF, 18V, Idss>3,7mA	5(DSG1G2)	Tos	—
3SK283	GaAs-N-FET-d	SMD, Dual-Gate, UHF-TV-Tuner, 6V	44l	Tos	—
3SK284	GaAs-N-FET-d	=3SK283	44l(2mm)	Tos	—
3SK288	MOS-N-FET-d	SMD, Dual-Gate, VHF, 12V, 25mA	44l	Hit	—
3SK29	MOS-N-FET-d	Chopper, Uni, 20V, Idss=1mA, Up<5V	5n	Nec	—
3SK290	MOS-N-FET-d	SMD, Dual-Gate, UHF, 12V, 25mA	44l(2mm)	Hit	—
3SK295	MOS-N-FET-d	SMD, Dual-Gate, UHF, 12V, 25mA	44l	Hit	—
3SK296	MOS-N-FET-d	=3SK295	44l(2mm)	Hit	—
3SK297	MOS-N-FET-d	SMD, Dual-Gate, VHF, 12V, 25mA	44l	Hit	—
3SK296	MOS-N-FET-d	=3SK297	44l(2mm)	Hit	—
3SK30(A)	N-FET	Dual-Gate, AM/FM, 15V, Idss>3mA, Up<5V	5(DSG1G2)	Hit	—
3SK32	MOS-N-FET-d	Dual-Gate, FM/VHF, 20V, Idss<5mA, Up<2,5V	5g	Mat	3SK39, 3SK70, 3SK80
3SK33	MOS-N-FET-d	FM/VHF, 25V, Idss>4mA, Up<4V	5m	Nec	—
3SK35	MOS-N-FET-d*	Dual-Gate, VHF, 20V, Idss>3mA, Up<4V	5h	Tos	BF350, BF900, 3SK40
3SK37	MOS-N-FET-d*	Dual-Gate, VHF, 20V, Idss>4mA, Up<3V	5h	Son	BF961, 3SK37, 3SK45, 3SK61, 3SK77
3SK38(A)	MOS-N-FET-e*	Dual-Gate, Chopper, 10V, Up<3V	5o	Tos	—
3SK39	MOS-N-FET-d	Dual-Gate, VHF, 20V, Idss>1mA, Up<3V	5h	Mat	3SK70, 3SK80
3SK40	MOS-N-FET-d	Dual-Gate, VHF, 20V, Idss>4mA, Up<4V	5h	Nec	BF350..351, BF900, 3N201..206,++
3SK41	MOS-N-FET-d	Dual-Gate, VHF, 20V, Idss>4mA, Up<4V	6h	Nec	BF350..351, BF900, 3N201..206,++
3SK44	MOS-N-FET-d	Dual-Gate, VHF, 20V, Idss>3mA, Up<3,3V	5h	Tos	BF981, 3SK37, 3SK45, 3SK61, 3SK77
3SK45	MOS-N-FET-d	Dual-Gate, VHF, 22V, Idss>4mA, Up<3V	5h	Hit	BF961, 3SK37, 3SK61, 3SK77
3SK47	MOS-N-FET-d	Dual-Gate, VHF, 20V, Idss>4mA, Up<3V	5h	Nec	BF960..982, 3SK37, 3SK45, 3SK61, 3SK77
3SK48	MOS-N-FET-d	Dual-Gate, UHF, 18V, Idss>2mA, Up<3V	5h	Son	BF960, BF965...966
3SK49	MOS-N-FET-d	Dual-Gate, VHF, 20V, Idss>2,5mA, Up<3V	5h	Mat	BF981, 3SK37, 3SK45, 3SK61, 3SK77
3SK51	MOS-N-FET-d	Dual-Gate, VHF, 20V, Idss>8mA, Up<3V	5h	Hit	3SK74
3SK53	MOS-N-FET-d	Dual-Gate, UHF, 20V, Idss>0,1mA, Up<1,7V	5h	Hit	3SK115
3SK55	MOS-N-FET-d	Dual-Gate, VHF, 20V, Idss>3mA, Up<2,5V	5h	Tos	BF981, 3SK37, 3SK45, 3SK61, 3SK77
3SK59	MOS-N-FET-d*	Dual-Gate, FM/VHF, 20V, Idss>3mA, Up<2,5V	5h	Toa	BF981, 3SK37, 3SK45, 3SK61, 3SK77
3SK60	MOS-N-FET-d	Dual-Gate, VHF, 15V, Idss<20mA, Up<1,7V	5h	Hit	BF980..962, 3SK47
3SK61	MOS-N-FET-d	Dual-Gate, VHF, 20V, Idss>4mA, Up<3V	5h	Son	BF981, 3SK37, 3SK45, 3SK77
3SK62	N-FET	Dual-Source, NF-V, 20V, Idss<0,5mA		Tos	—
3SK63	MOS-N-FET-d*	Dual-Gate, VHF, 20V, Idss>3mA, Up<2,5V	5h	Tos	BF961, 3SK37, 3SK45, 3SK61, 3SK77
3SK66	MOS-N-FET-d	Dual-Gate, UHF, 20V, Idss>0,5mA, Up<3V	5h	Mat	3SK79, 3SK67, 3SK100
3SK70	MOS-N-FET-d	Dual-Gate, VHF, UHF, 20V, Idss>1mA, Up<3V	5h	Hit	BF960, BF965..966, 3SK48, 3SK80
3SK71	N-FET	NF-V, 20V, Idss<0,5mA		Nec	—
3SK72	MOS-N-FET-d	Dual-Gate, VHF, 20V, Idss>2,5mA, Up<3V	25g	Mat	BF961, 3SK37, 3SK45, 3SK81, 3SK77
3SK73	MOS-N-FET-d*	Dual-Gate, VHF, 20V, Idss>3mA, Up<2,5V	≈42	Tos	BF981, 3SK37, 3SK45, 3SK61, 3SK77
3SK74	MOS-N-FET-d	Dual-Gate, VHF, 20V, Idss>7mA, Up<3V	25g	Nec	3SK51
3SK76	MOS-N-FET-d	Dual-Gate, 14V, Idss>5mA, Up<1V	5h	Son	—
3SK77	MOS-N-FET-d	Dual-Gate, VHF, 20V, Idss>3mA, Up<2,5V	≈42	Tos	BF961, 3SK37, 3SK45, 3SK61
3SK78	MOS-N-FET-d	Dual-Gate, VHF/UHF, 20V, Idss>3mA, Up<3.5V	5h, 52	Tos	BF900, 3N209..210
3SK79	MOS-N-FET-d	Dual-Gate, UHF, 20V, Idss>0,5mA, Up<3V	25g	Mat	3SK66, 3SK87, 3SK100
3SK80	MOS-N-FET-d	Dual-Gate, UHF, 20V, Idss>1mA, Up<3V	25g	Hit	BF960, BF965..966, 3SK48, 3SK70
3SK81	MOS-N-FET-d	Dual-Gate, VHF, 20V, Idss>5mA, Up<3V	25g	Hit	BF352..353, BF963, 3SK51, 3SK74
3SK82	MOS-N-FET-d	Dual-Gate, UHF, 15V, Idss<20mA, Up<1,7V	25g	Hit	BF980
3SK83	MOS-N-FET-d	Dual-Gate, VHF, 15V, Idss<20mA, Up<1,7V	25g	Hit	BF962, 3SK47
3SK85	MOS-N-FET-d	Dual-Gate, VHF, 22V, Idss>4mA, Up<3V	25g	Hit	BF961, 3SK37, 3SK45, 3SK61, 3SK77
3SK87	MOS-N-FET-d	Dual-Gate, UHF, 20V, Idss>0,5mA, Up<2V	25g	Nec	3SK66, 3SK79, 3SK100
3SK88	MOS-N-FET-d	Dual-Gate, UHF, 20V, Idss>0,01mA, Up<2V	25g	Nec	3SK123
3SK90	MOS-N-FET-e	Dual-Gate, Chopper, 20V, Up<3V	5o	Tos	—
3SK95	MOS-N-FET-d	Dual-Gate, UHF, 15V, Idss<30mA, Up<2V	25g	Hit	BF980
3SK96	MOS-N-FET-d	Dual-Gate, VHF, 15V, Idss<30mA, Up<2V	25g	Hit	BF352..353, BF983, 3SK81
3SK97	GaAs-N-FET	Dual-Gate, UHF, 15,5V, Idss=380mA	25g	Mat	—
3SS	Si-N	=MMBTA28(Typ-Code/Stempel/marking)	35		→MMBTA28
3SS3M	F-Thy	300V, 3A(Tc=70°C), Igt<30mA	13e	Nec	(TAG650S-.., TAG655S-.., CSF11-..)
3SS4M	F-Thy	=3SS3M, 400V	13e		(TAG650S-.., TAG655S-.., CSF11-..)
3 T		**3T...3Z**			
3T	Si-P	=HT3(Typ-Code/Stempel/marking)	35		→HT3
3TE120	Si-N	AM-L, 90V, 12A, PQ=50W(70MHz)	23a	Itt	—
3TE130	Si-N	AM-L, 90V, 5A, PQ=30W(70MHz)	23a	Itt	—
3TE220	Si-N	VHF-L, 80V, 5A, PQ=50W(150MHz)	23a	Itt	—
3TE230	Si-N	VHF-L, 80V, 4A, PQ=30W(150MHz)	23a	Itt	—
3TE240	Si-N	VHF-L, 80V, 3A, >200MHz	23a	Itt	—
3TE440	Si-N	VHF/UHF-L, 80V, 1,5A, >350MHz		Itt	—
3TE450	Si-N	VHF/UHF-L, 80V, 0,5A, >350MHz		Itt	—

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3TX002	Si-N	AM-L, 100V, 5A, >150MHz	23a	Itt	—
3TX003	Si-N	AM-L, 100V, 5A, >150MHz	23a	Itt	—
3TX004	Si-N	AM-L, 60V, 5A, >150MHz	23a	Itt	—
3U	Si-N	=2SC3967 (Typ-Code/Stempel/marking)	35		→2SC3967
3U	Si-N	=2SC4068 (Typ-Code/Stempel/marking)	35(2mm)		→2SC4068
3W	Si-N	=FMMT-A12(Typ-Code/Stempel/marking)	35		→FMMT-A12
3WS	Si-N	=2SD1938-S (Typ-Code/Stempel/marking)	35		→2SD1938
3WS	Si-N	=2SD1979-S (Typ-Code/Stempel/marking)	35(2mm)		→2SD1979
3WS	Si-N	=2SD2529-S (Typ-Code/Stempel/marking)	≈35		→2SD2529
3WT	Si-N	=2SD1938-T (Typ-Code/Stempel/marking)	35		→2SD1938
3WT	Si-N	=2SD1979-T (Typ-Code/Stempel/marking)	35(2mm)		→2SD1979
3WT	Si-N	=2SD2529-T (Typ-Code/Stempel/marking)	≈35		→2SD2529
3Y	Si-N	=2SC5190 (Typ-Code/Stempel/marking)	35(2mm)		→2SC5190
3Y0	Z-Di	=BZV49/C3V0(Typ-Code/Stempel/marking)	39		→BZV49/C3V0
3Y3	Z-Di	=BZV49/C3V3(Typ-Code/Stempel/marking)	39		→BZV49/C3V3
3Y6	Z-Di	=BZV49/C3V6(Typ-Code/Stempel/marking)	39		→BZV49/C3V6
3Y9	Z-Di	=BZV49/C3V9(Typ-Code/Stempel/marking)	39		→BZV49/C3V9
3Z12..390	Z-Di	TAZ, Z, 12..390V, 1,5kW(1ms)	31a	Tos	1N5635..5665, 1N6273..6303
3ZP	MOS-N-FET-d	=3SK193-P (Typ-Code/Stempel/marking)	44		→3SK193
3ZQ	MOS-N-FET-d	=3SK193-Q (Typ-Code/Stempel/marking)	44		→3SK193

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4	C-Di	=HVU350 (Typ-Code/Stempel/marking)	71 (1,7mm)		→HVU350
4,3B	Z-Di	=HZF 4.3BP (Typ-Code/Stempel/marking)	71 (5mm)		→HZF 43BP
4,3C	Z-Di	=HZF 4.3CP (Typ-Code/Stempel/marking)	71 (5mm)		→HZF 43CP
4,7B	Z-Di	=HZF 4.7BP (Typ-Code/Stempel/marking)	71 (5mm)		→HZF 47BP
4,7C	Z-Di	=HZF 4.7CP (Typ-Code/Stempel/marking)	71 (5mm)		→HZF 47CP
4000	CMOS-Logic	Dual 3-Input NOR Gate, 1 Inverter	14-DIP		—
4000	CMOS-Logic		20-MP		—
40004	Ge-P	HF, 40V, 10mA, 30MHz	4g	Sty	AF124..127, AF200
40005	Ge-P	HF, 40V, 10mA, 100MHz	4g	Sty	AF124..125, AF200
40006	Ge-P	HF, 40V, 10mA, 120MHz	4g	Sty	AF124..125, AF200
4001	CMOS-Logic	Quad 2-Input NOR Gate	14-DIP		—
4001	CMOS-Logic		20-MP		—
40014	CMOS-Logic	Hex Schmitt Trigger Inverter	14-DIP		—
4002	CMOS-Logic	Dual 4-Input NOR Gate	14-DIP		—
4002	CMOS-Logic		20-MP		—
40022	Ge-P	NF/S-L, 32V, 5A, 12,5W(Tc=75°)	23a	Rca,Sty,++	AL102..103, AUY26, 2N1539..46,++
40050	Ge-P	NF/S-L, 40V, 5A, 12,5W(Tc=75°)	23a	Gpd,Rca,Sty	AL102..103, AUY28, 2N1539..48,++
40051	Ge-P	=40050: 50V	23a	Gpd,Rca,Sty	AL102..103, AUY2S, 2N1540..43,++
40053	Si-N	≈2N3053	2a	Rca	→2N3053
4006	CMOS-Logic	Shift Register with variable Length	14-DIP		—
4006	CMOS-Logic	(max 16 Bit)	20-MP		—
4007	CMOS-Logic	Dual Complementary Pair, 1 Inverter	14-DIP		—
4007	CMOS-Logic		20-MP		—
4006	CMOS-Logic	4-Bit Full Adder	16-DIP		—
4006	CMOS-Logic		20-MP		—
40080	Si-N	AM-Tr, -/30V, 0,25A, PQ>0,1W(27MHz)	2a	Rca,Sty,++	MRF402, MRF8003
40081	Si-N	AM-Tr, 60V, 0,25A, PQ>0,4W(27MHz)	2a	Rca,Sty,++	MRF402, MRF8003
40082	Si-N	AM-Tr, 60V, 1,5A, PQ>3W(27MHz)	2a	Rca,Sty,++	—
40084	Si-N	NF/S, 60V, 1A, 0,5A, >100MHz, <30/-ns	2a	Rca,Sca,Sty	BSS2S, BSS40..41, 2N4014
40065	CMOS-Logic	4-Bit Comparator	16-DIP		—
4009	CMOS-Logic	Hex Inverter/Buffer	16-DIP		—
4009	CMOS-Logic		20-MP		—
40097	CMOS-Logic	Hex Buffer/Driver, non inverting	16-DIP		—
40096	CMOS-Logic	Hex Inverter	16-DIP		—
4010	CMOS-Logic	Hex Buffer, non inverting	16-DIP		—
4010	CMOS-Logic		20-MP		—
40100	CMOS-Logic	32-Bit Serial Shift Register,	16-DIP		—
40100	CMOS-Logic	right/left shifting	20-MP		—
40101	CMOS-Logic	9-Bit Parity Generator/Parity Checker	14-DIP		—
40101	CMOS-Logic		20-MP		—
40102	CMOS-Logic	Synchronous 2-Decade Down Counter	16-DIP		—
40102	CMOS-Logic	with Preset	20-MP		—
40103	CMOS-Logic	Asynchronous 8-Bit Down Counter with	16-DIP		—
40103	CMOS-Logic	Preset	20-MP		—

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40104	CMOS-Logic	4-Bit Shift Register with parallel	16-DIP		—
40104	CMOS-Logic	Input/Output, right/left shifting	20-MP		—
40105	CMOS-Logic	16x4-Bit FIFO	16-DIP		—
40105	CMOS-Logic		20-MP		—
40106	CMOS-Logic	Hex Schmitt Trigger Inverter	14-DIP		—
40106	CMOS-Logic		20-MP		—
40107	CMOS-Logic	Dual 2-Input NAND Driver	8-DIP		—
40107	CMOS-Logic		20-MP		—
40106	CMOS-Logic	4x4-Bit Multiport Register	24-DIP		—
40106	Si-Di	GI-L, 50V, 10A(Tc=150°)	32a	Rca	BYX42/300, BYX98/300
40106R..40116R	Si-Di	=40106: 40116	32b		BYX42/..R, BYX98/..R
40109	Si-Di	=40108: 100V	32a		BYX42/300, BYX98/300
40109	CMOS-Logic	Quad Level-Changer, noninverting	16-DIP		—
40109	CMOS-Logic		20-MP		—
4011	CMOS-Logic	Quad 2-Input NAND Gate	14-DIP		—
4011	CMOS-Logic		20-MP		—
40110	CMOS-Logic	Decimal Up/Down Counter with	16-DIP		—
40110	CMOS-Logic	Register, 7-Segment-Decoder and Driver	20-MP		—
40110	Si-Di	=40106: 200V	32a		BYX42/300, BYX98/300
40111	Si-Di	=40106: 300V	32a		BYX42/300, BYX98/300
40112	Si-Di	=40106: 400V	32a		BYX42/600, BYX98/600
40113	Si-Di	=40108: 500V	32a		BYX42/600, BYX98/600
40114	Si-Di	=40106: 600V	32a		BYX42/600, BYX98/600
40115	Si-Di	=40108: 800V	32a		BYX42/900, BYX98/900
40116	Si-Di	=40106: 1000V	32a		BYX42/1200, BYX98/1200
40117	CMOS-Logic	Dual 4-Bit Data Switch	14-DIP		—
4012	CMOS-Logic	Dual 4-Input NAND Gate	14-DIP		—
4012	CMOS-Logic		20-MP		—
4013	CMOS-Logic	Dual D-Flip-Flop with Complementary	14-DIP		—
4013	CMOS-Logic	Outputs With Preset and Clear	20-MP		—
4014	CMDS-Logic	8-Bit Shift Register with parallal	16-DIP		—
4014	CMOS-Logic	Inputs and Clear	20-MP		—
40147	CMOS-Logic	BCD Priority Encoder	16-DIP		—
40147	CMOS-Logic		20-MP		—
4015	CMOS-Logic	Dual 4-Bit Shift Register with	16-DIP		—
4015	CMOS-Logic	parallel Outputs	20-MP		—
4016	CMOS-Logic	Quad Bilateral Digital or Analog	14-DIP		—
4016	CMOS-Logic	Switch (4x1 Closer)	20-MP		—
40160	CMOS-Logic	Synchronous Decimal Up/Down Counter	16-DIP		—
40160	CMOS-Logic	with Preset and Clear	20-MP		—
40161	CMOS-Logic	Synchronous Binary 4-Bit Up Counter	16-DIP		—
40161	CMOS-Logic	with Preset and Clear	20-MP		—
40162	CMOS-Logic	Synchronous Decimal Up/Down Counter	16-DIP		—
40162	CMOS-Logic	with Preset and Clear	20-MP		—
40163	CMOS-Logic	Synchronous Binary 4-Bit Up Counter	16-DIP		—
40163	CMOS-Logic	with Preset and Clear	20-MP		—
4017	CMOS-Logic	Synchronous Decimal Up Counter with	16-DIP		—
4017	CMOS-Logic	Decimal-Decoder	20-MP		—
40174	CMOS-Logic	6-Bit D-Register with Clear, non	16-DIP		—
40174	CMOS-Logic	inverting	20-MP		—
40175	CMOS-Logic	4-Bit D-Register with Clear, non	16-DIP		—
40175	CMOS-Logic	inverting			—
4018	CMOS-Logic	4-Bit Programmable Divider/Counter	18-DIP		—
4018	CMOS-Logic		20-MP		—
40181	CMOS-Logic	4-Bit Arithmetic/Logic Unit (ALU)	24-DIP		—
40182	CMOS-Logic	Carry Unit for 74160, 74163, 74181,	16-DIP		—
40182	CMOS-Logic	74281, 74381	20-MP		—
4019	CMOS-Logic	Quad 2-to-1 common addressable Data	16-DIP		—
4019	CMOS-Logic	Selector/Multiplexer	20-MP		—
40192	CMOS-Logic	Synchronous Decimal Up/Down Counter	18-DIP		—
40192	CMOS-Logic	with Preset	20-MP		—
40193	CMOS-Logic	Synchronous Binary 4-Bit Up/Down	16-DIP		—
40193	CMOS-Logic	Counter with Preset	20-MP		—
40194	CMOS-Logic	4-Bit Shift Register with parallel	16-DIP		—
40194	CMOS-Logic	Input/Output, right/left with Clear	20-MP		—
40195	CMOS-Logic	4-Bit Universal Shift Register	16-DIP		—

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4020	CMOS-Logic	Asynchronous Binary 14-Bit Up Counter	16-DIP		—
4020	CMOS-Logic		20-MP		—
40208	CMOS-Logic	4x4-Bit Multiport Register	24-DIP		—
40208	Si-Di	GI-L, 50V, 18A(Tc=150°)	32a	Rca	1N4525..30
40208R..40214R	Si-Di	=40208: 40214	32b		D24/..C
40209	Si-Di	=40208: 100V	32a		1N4525..30
4021	CMOS-Logic	8-Bit Shift Register with parallel	16-DIP		—
4021	CMOS-Logic	Inputs and Clear	20-MP		—
40210	Si-Di	=40208: 200V	32a		1N4525..30
40211	Si-Di	=40208: 300V	32a		1N4526..30
40212	Si-Di	=40208: 400V	32a		1N4526..30
40213	Si-Di	=40208: 500V	32a		1N4527..30
40214	Si-Di	=40208: 600V	32a		1N4527..30
40216	F-Thy	=S6431M	21b	Rca	→S6431M
40217	Si-N	S, 25V, 0,3W, >200MHz	2a	Rca,Sty	BSS 11..12, BSX 19..20, 2N2368..69(A),++
40218	Si-N	S, 25V, 0,05A, 0,3W, >200MHz	2a	Rca,Sty	BSS 11..12, BSX 19..20, 2N2368..69(A),++
40219	Si-N	S, 40V, 0,36W, >300MHz	2a	Rca,Sty	BSS 11, BSX 19..20, 2N2368..69(A),++
4022	CMOS-Logic	Synchronous Octal Counter decoded	16-DIP		—
4022	CMOS-Logic	Outputs	20-MP		—
40220	Si-N	S, 40V, 0,2A, 0,3W, >350MHz	2a	Rca,Sty	BSS 11, BSX 19..20, 2N2368..69(A),++
40221	Si-N	S, 40V, 0,36W, >300MHz	2a	Rca,Sty	BSS 11, BSX 19..20, 2N2368..69(A),++
40222	Si-N	S, 25V, 0,2A, 0,3W, >200MHz	2a	Rca,Sty	BSS 11..12, BSX 19..20, 2N2368..69(A),++
4023	CMOS-Logic	Triple 3-Input NAND Gate	14-DIP		—
4023	CMOS-Logic		20-MP		—
40231	Si-N	NF, ra, 18V, 0,1A, 0,5W, 60MHz	2a	Rca,Sca,Sty	BC 169, BC 184, BC 239, BC 549,++
40232	Si-N	NF, ra, 18V, 0,1A, 0,5W, 60MHz	2a	Rca,Sca,Sty	BC 169, BC 184, BC 239, BC 549,++
40233	Si-N	NF, ra, 18V, 0,1A, 0,5W, 60MHz	2a	Rca,Sca,Sty	BC 169, BC 184, BC 239, BC 549,++
40234	Si-N	NF, ra, 18V, 0,1A, 0,5W, 60MHz	2a	Rca,Sca,Sty	BC 169, BC 184, BC 239, BC 549,++
40235	Si-N	VHF-V, 1000MHz	5g	Nsc,Rca,Sca	BF 314, BF 496, BF 502..503, BF 505,++
40236	Si-N	VHF-M, 1000MHz	5g	Nsc,Rca,Sca	BF 314, BF 496, BF 502..503, BF 505,++
40237	Si-N	VHF-O, 1000MHz	5g	Nsc,Rca,Sca	BF 314, BF 496, BF 502..503, BF 505,++
40238	Si-N	TV-ZF, re, 800MHz	5g	Nsc,Rca,Sca	BF 196, BF 225, BF 310, BF 367,++
40239	Si-N	TV-ZF, 600MHz	5g	Nsc,Rca,Sca	BF 199, BF 224, BF 311, BF 373,++
4024	CMOS-Logic	Asynchronous Binary 7-Bit Up Counter	14-DIP		—
4024	CMOS-Logic		20-MP		—
40240	Si-N	TV-ZF-E, 600MHz	5g	Nsc,Rca,Sca	BF 199, BF 224, BF 311, BF 373,++
40240	CMOS-Logic	8-Bit Bus Line Driver with 2 Enable	20-DIP		—
40240	CMOS-Logic	Inputs, inverting			—
40242	Si-N	FM-V, 900MHz	5g	Nsc,Rca,Sca	BF 241, BF 255, BF 495, BF 595,++
40243	Si-N	FM-M, 850MHz	5g	Nsc,Rca,Sca	BF 241, BF 255, BF 495, BF 595,++
40244	Si-N	FM-O, 800MHz	5g	Nsc,Rca,Sca	BF 240, BF 254, BF 494, BF 594,++
40244	CMOS-Logic	2x4-Bit Bus Driver with Separate	20-DIP		—
40244	CMOS-Logic	Enable Inputs, non inverting			—
40245	CMOS-Logic	Quad Bus Transceiver, non inverting	20-DIP		—
40245	Si-N	FM-ZF, 600MHz	5g	Nsc,Rca,Sca	BF 240, BF 254, BF 494, BF 594,++
40246	Si-N	FM-ZF, 600MHz	5g	Nsc,Rca,Sca	BF 240, BF 254, BF 494, BF 594,++
4025	CMOS-Logic	Triple 3-Input NOR Gate	14-DIP		—
4025	CMOS-Logic		20-MP		—
40250	Si-N	NF/S-L, 50V, 4A, 29W, 1MHz	22a	Rca,Sgs,++	BD 243, BD 535, BD 539A, 2N3054,++
40250 V1	Si-N	=40250:	22a°		→40250
40251	Si-N	NF/S-L, 50V, 15A, 117W, 0,5MHz	23a	Rca,Sgs,++	BD 315, BD 545A, BDX 13, 2N3055,++
40253	Ge-P	NF-Tr/E, 25V, 0,5A, 0,125W	2a	Rca,Sty	AC 128, AC 152..153, AC 188, 2SB405,++
40254	Ge-P	NF-L, 32V, 5A, 12,5W(Tc=75°)	23a	Gpd,Rca,++	AL 102..103, AUY 28, 2N1539..46,++
40255	Si-N	NF/S-L, 450/350V, 1A, 10W, >20MHz	43a	Rca,Sty	BD 410, BUW 40(A,B), TIP 49..50,++
40256	Si-N	=40255: 300/250V	43a	Rca,Sty	BD 410, BUW 40(A,B), TIP 47..50,++
40257	CMOS-Logic	Quad 2-to-1 Data Selector/Multiplexer	16-DIP		—
40257	CMOS-Logic		20-MP		—
4026	CMOS-Logic	Decimal Up Counter with	16-DIP		—
4026	CMOS-Logic	7-Segment-Decoder	20-MP		—
40261	Ge-P	AM-V/M/O, 40MHz	2a	Rca,Sty	AF 124..127, AF 200
40262	Ge-P	AM-ZF, 30MHz	2a	Rca,Sty	AF 124..127, AF 200
40263	Ge-P	NF, 20V, 0,05A, 0,12W	2a	Rca,Sty	AC 125, AC 126, AC 151
40264	Si-N	NF/Vid-E, 300/300V, 0,1A, 4W, 25MHz	≈22	Rca,Sty	(BF 459, BF 859, 2SC1505..1507,++)
40268	Ge-P	HF, 25V, 0,1A, 0,1W, >250MHz	2a	Rca,Sty	(AF 139, AF 239(S))
40269	Ge-P	NF/S, 25V, 0,1A, 0,15W, >4MHz	2a	Rca,Sty	AC 125..126, AC 151, ASY 26..27
4027	CMOS-Logic	Dual Positive Edge-Triggered JK	16-DIP		—

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4027	CMOS-Logic	Flip-Flop with Preset and Clear	20-MP		—
40279	Si-N	=2N3375: hi-rel	49a	Rca,Ssi	→2N3375
4028	CMOS-Logic	BCD-to-Decimal Decoder	16-DIP		—
4028	CMOS-Logic		20-MP		—
40280	Si-N	VHF-Tr/E, 36V, 0,5A, PQ>1W(175MHz)	2a	Rca,Sca,Sty	BFQ42, BFR98, BLW16, BLY61
40281	Si-N	VHF-L, 36V, 1A, PQ>4W(175MHz)	49a	Rca,Sca,Sty	BLY57, BLY78, 2N3926
40282	Si-N	VHF-L, 36V, 2A, PQ>12W(175MHz)	49a	Rca,Sca,Sty	BLY58, 2N3927
40283	Si-N	S, 60V, 1A, 0,4W, <30/45ns	2a	Rca,Sca,Sty	2N4014
4029	CMOS-Logic	Synchronous Binary 4-Bit Up/Down	16-DIP		—
4029	CMOS-Logic	Counter with Preset	20-MP		—
40290	Si-N	FM/VHF-Tr/E, 50V, 0,5A, PQ>2W(135MHz)	2a	Rca,Sty,++	BFW46, BLY33, 2N3924
40291	Si-N	FM/VHF-L, 50V, 0,5A, PQ>2W(135MHz)	49a	Rca,Sty,++	BLY55
40292	Si-N	FM/VHF-L, 50V, 1,25A, PQ>6W(135MHz)	49a	Rca,Sty,++	BLY57, 2N3926
40294	Si-N	=2N2857: hi-rel	5g	Rca,Sty	→2N2857
40295	Si-N	=2N2708: hi-rel	5g	Rca,Sty	→2N2708
40298	Si-N	=2N3839: hi-rel	5g	Rca,Sty	→2N3839
4030	CMOS-Logic	Quad 2-Input EX-OR Gate	14-DIP		—
4030	CMOS-Logic		20-MP		—
40305	Si-N	=2N3553: hi-rel	2a	Rca,Ssi,Sty	→2N3553
40308	Si-N	=2N3375: hi-rel	49a	Rca,Ssi,Sty	→2N3375
40307	Si-N	=2N3632: hi-rel	49a	Rca,Ssi,Sty	→2N3632
40309(L,S)	Si-N	NF-Tr-/18V, 0,7A, 1W, 100MHz	2a	Rca,Sty,++	BC140..141, BC300..302, 2N3053,++
40309V1	Si-N	=40309(L,S):	2a°		(BD137, BD228, BD517, BD527,++)
40309V2	Si-N	=40309(L,S):	43m		(BD137, BD228, BD517, BD527,++)
4031	CMOS-Logic	64-Bit Serial Shift Register	16-DIP		—
4031	CMOS-Logic		20-MP		—
40310	Si-N	NF-L, -/35V, 4A, 29W, 0,75MHz	22a	Rca,Sty,++	BD243, BD533, BD539, BD947,++
40310V1	Si-N	NF-L, -/35V, 4A, 29W, 0,75MHz	22a°		BD243, BD533, BD539, BD947,++
40311(L,S,V1,V2)	Si-N	=40309: -/30V		Rca,Sty,++	→40309(L,S,V1,V2)
40312(V1)	Si-N	=40310: 60V	22a(°)	Rca,Sty,++	BD243A, BD535, BD539A, BD949,++
40313	Si-N	NF-L, 300V, 2A, 35W	22a	Rca,Sty	BUX87A..C, TIP75(A..C), 2SC782,++
40314(L,S)	Si-N	NF-Tr, -/40V 0,7A, 1W, 100MHz	2a	Rca,Sty,++	BC140..141, BC300..302, 2N3053,++
40314V1	Si-N	=40314(L,S):	2a°		(BD137, BD228, BD517, BD527,++)
40314V2	Si-N	=40314(L,S):	43m		(BD137, BD228, BD517, BD527,++)
40315(L,S,V1,V2)	Si-N	=40314: -/35V		Rca,Sty,++	→40314(L,S,V1,V2)
40316	Si-N	NF-L, 40V, 4A, 29W, 0,75MHz	22a	Rca,Sty,++	BD243A, BD535, BD539A, BD949,++
40317(L,S,V1,V2)	Si-N	=40309: -/40V		Rca,Sty,++	→40309(L,S,V1,V2)
40318	Si-N	NF-L, 300V, 2A, 35W	22a	Rca,Sty,++	BUX87A..C, TIP75(A..C), 2SC782,++
40319(L,S)	Si-P	NF-Tr, -/40V, 0,7A, 1W, 100MHz	2a	Rca,Sty,++	BC160..161, BC303..304, 2N2303,++
40319V1	Si-P	=40319(L,S):	2a°		(BD138, BD229, BD518, BD528,++)
40319V2	Si-P	=40319(L,S):	43m		(BD138, BD229, BD518, BD526,++)
4032	CMOS-Logic	Triple Serial Adder (Positive Logic)	16-DIP		—
4032	CMOS-Logic		20-MP		—
40320(L,S,V1,V2)	Si-N	=40314: B>40		Rca,Sty,++	→40314(L,S,V1,V2)
40321(L,S)	Si-N	NF/Vid, 300V, 1A, 1W	2a	Rca,Sty,++	BFQ38..39, BSS48..49, 2N3440, 2SC1881+
40321V1	Si-N	=40321(L,S):	2a°		(BD410, BUV63, BUW40, TIP47..50,++)
40321V2	Si-N	=40321(L,S):	43m		(BD410, BUV83, BUW40, TIP47..50,++)
40322	Si-N	=40318	22a	Rca,Sty,++	→40318
40323(L,S,V1,V2)	Si-N	=40309		Rca,Sty,++	→40309(L,S,V1,V2)
40324	Si-N	=40310	22a	Rca,Sty,++	→40310
40325	Si-N	NF-L, 35V, 15A, 117W	23a	Rca,Sty,++	BD315, BD545, BD745, 2N3055,++
40328(L,S,V1,V2)	Si-N	=40309: -/40V		Rca,Sty,++	→40309(L,S,V1,V2)
40327(L,S,V1,V2)	Si-N	=40321		Rca,Sty,++	→40321(L,S,V1,V2)
40328	Si-N	=40318	22a	Rca,Sty,++	→40318
40329	Ge-P	NF/S, 25V, 0,1A, 0,125W	2a	Rca,Sty	AC125..126, AC151, ASY26..27
4033	CMOS-Logic	Decimal Up Counter with	16-DIP		—
4033	CMOS-Logic	7-Segment-Decoder and ripple blanking	20-MP		—
4034	CMOS-Logic	8-Bit Bidirectional Bus Register	24-DIP		—
40340	Si-N	FM/VHF-L, 60V, 3,3A, PQ>25W(50MHz)	49a	Rca,Ssi	—
40341	Si-N	FM/VHF-L, 70V, 3,3A, PQ>30W(50MHz)	49a	Rca,Ssi	—
40342	Si-N	HF-L, 65V, 3A, 23W	49a	Rca	—
40343	Si-N	HF-L, 65V, 3A, 23W	49a	Rca	—
40346(L,S)	Si-N	NF/S, 175V, 1A, 1W, >10MHz	2a	Rca,Sty,++	BFQ38..39, BSS48..49, 2N3440, 26C1881+
40346V1	Si-N	=40346(L,S):	2a°		(BD410, BUW40, 2SC3117, 2SD689,++)
40346V2	Si-N	=40346(L,S):	43m		(BD410, BUW40, 2SC3117, 2SD669,++)
40347(L,S)	Si-N	NF/S, 60V, 1,5A	2a	Rca,Sty,++	BCX40, BSS42..43, (BD139, BD529,++)

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40347 V1	Si-N	=40347(L,S):	2a°		(BD139, BD237, BD529, BD843,++)
40347 V2	Si-N	=40347(L,S):	43m		(BD139, BD237, BD529, BD843,++)
40348(L,S,V1,V2)	Si-N	=40347: 90V		Rca,Sty,++	→40347(L,S,V1,V2)
40349(L,S,V1,V2)	Si-N	=40347: 160V		Rca,Sty,++	(BD410, BD443A, 2SC3117, 2SD669,++)
4035	CMOS-Logic	4-Bit Shift Register with parallel	16-DIP		—
4035	CMOS-Logic	Inputs/Outputs and Clear	20-MP		—
40350	Si-N	UHF	5g	Sty	BF377..378, BF689, BF763, 2N2857,++
40351	Si-N	UHF	5g	Sty	BF377..378, BF689, BF763, 2N2857,++
40352	Si-N	UHF	5g	Sty	BF377..378, BF689, BF763, 2N2857,++
40354	Si-N	Vid,-/50V, 0,05A, 0,5W, 100MHz	2a	Rca	BF287..299, BFR87..89, 2SC3467,++
40355	Si-N	=40354: 1W	2a°	Rca	BF297..299, BFR87..89, 2SC3467,++
40359	Ge-P	NF, 20V, 0,05A, 0,12W	2a	Rca, Sty	AC125..128, AC151, ASY26..27
4036	CMOS-Logic	4x8-Bit RAM	24-DIP		—
40360(L,S)	Si-N	NF-Tr, 70V, 0,7A, 1W, 100MHz, B>40	2a	Rca,Sty,++	BC140..141, BC300..301, 2N1990,++
40360 V1	Si-N	=40360(L,S):	2a°		(BD139, BD230, BD519, BD529,++)
40360 V2	Si-N	=40360(L,S):	43m		(BD139, BD230, BD519, BD529,++)
40361 (L,S,V1,V2)	Si-N	=40360: B>70		Rca,Sty,++	→40360(L,S,V1,V2)
40362(L,S)	Si-P	NF-Tr, 70V, 0,7A, 1W, 100MHz	2a	Rca,Sty,++	BC161, BC303, BCX60, 2SA606,++
40362 V1	Si-P	=40362(L,S):	2a°		(BD140, BD231, BD520, BD530,++)
40362 V2	Si-P	=40362(L,S):	43m		(BD140, BD231, BD520, BD530,++)
40363	Si-N	NF-L, 70V, 15A, 115W, 0,7MHz	23a	Rca,Sty,++	BD315, BD545B, BD745B, 2N3055,++
40364	Si-N	NF-L, 60V, 7A, 35W, 15MHz	22a	Rca,Sty,++	BD243A, BD543A, BD807, 2N6315..16,++
40366(L,S)	Si-N	=2N2102: hi-rel	2a	Rca,Sty,++	→2N2102
40366 V1	Si-N	=40366(L,S):	2a°		(BD424, 2SC2275, 2SC2384, 2SC2690(A)++)
40366 V2	Si-N	=40366(L,S):	43m		(BD424, 2SC2275, 2SC2384, 2SC2690(A)++)
40367(L,S)	Si-N	NF-Tr/E, 100V, 1,5A, 1W	2a	Rca,Sty	BCX40, BSW66..88, BSX46..47,++
40367 V1	Si-N	=40367(L,S):	2a°		(BD139, BD230, BD529, BD843,++)
40367 V2	Si-N	=40367(L,S):	43m		(BD139, BD230, BD528, BD843,++)
40366	Si-N	NF/S-L, 100V, 3A, 25W	2a	Rca, Sty	(BD241C, BD539C, BD939, 2SD712,++)
40369	Si-N	NF/S-L, 100V, 6A, 75W	23a	Rca,Ssi,Sty	BD245C, BDV91, BDX91, 2N5758..59,++
4037	CMOS-Logic	Triple AND/OR Combination-Gate	14-DIP		—
40372	Si-N	=2N3054: 5,8W	22a°	Rca, Sty	→2N3054
40373	Si-N	=2N3441: 5,8W	22a°	Rca, Sty	→2N3441
40373	CMOS-Logic	8-Bit D-Latch with Enable, non	20-DIP		—
40373	CMOS-Logic	inverting			—
40374	CMOS-Logic	8-Bit D-Register with Clockenable,	20-DIP		—
40374	CMOS-Logic	noninverting			—
40374	Si-N	=2N3583: 5,8W	22a°	Rca,Sty	→2N3583
40375	Si-N	=2N3678: 5,8W	22a°	Rca,Sty	→2N3876
40378	50Hz-Thy	=S 2600B	2a	Rca	→S 2600B
40379	50Hz-Thy	=S 2800D	2a	Rca	→S 2600D
4038	CMOS-Logic	Triple Serial Adder (Negative Logic)	16-DIP		—
4036	CMOS-Logic		20-MP		—
40385(L,S)	Si-N	=2N3439: hi-rel	2a	Rca, Sca	→2N3439
40365 V1	Si-N	=2N3439:	2a°		→2N3439
40385 V2	Si-N	=2N3439:	43m		→2N3439
40389	Si-N	=2N3053: 3,5W	2a°	Rca,Sty	→2N3053
4039	CMOS-Logic	4x8-Bit RAM	24-DIP		—
40390	Si-N	=2N3440: 3,5W	2a°	Rca,Sty	→2N3440
40391	Si-P	=2N4037: 3,5W	2a°	Rca,Sty,++	→2N4037
40392	Si-N	=2N3053: 7W(Tc=25°)	43m	Rca,Sty,++	→2N3053
40393	Si-N	=2N3440: 10W(Tc=25°)	43m	Rca	→2N3440
40394	Si-P	=2N4037: 7W(Tc=25°)	43m	Rca,Sty,++	→2N4037
40395	Ge-P	NF-E, 18V, 0,5A, 0,3W	2a	Rca,Sca,Sty	AC128, AC152..153, AC188
40396	Ge-N	NF-E, 18V, 0,5A, 0,3W	2a	Rca,Sty	AC127, AC176, AC187
40397	Si-N	NF, 25V, 0,2A, 0,5W, 50MHz, β>165	2a	Rca,Sca,Sty	BC166, BC183, BC236, BC548,++
40398	Si-N	=40397: β>75	2a	Rca,Sca,Sty	BC166, BC183, BC236, BC548,++
40399	Si-N	=40397: 18V	2a	Rca,Sca,Sty	BC166, BC183, BC236, BC548,++
4040	CMOS-Logic	Asynchronous Sinary 12-Sit Up Counter	16-DIP		—
4040	CMOS-Logic		20-MP		—
40400	Si-N	=40397: 18V, β>75	2a	Rca,Sca,Sty	BC166, BC183, BC236, BC548,++
40403	Ge-P	NF/S, 30V, 0,2A, 0,2W, <850/1200ns	2a	Rca,Sty	AC125..128, AC151, ASY28
40404	Si-N	FM/VHF, 40V, 0,5A, PQ>0,05W(66MHz)	2a	Rca,Sty	MRF604, 2SC2053
40405	Si-N	VHF, 40V, 0,5A, PQ>0,2W(172MHz)	2a	Rca,Sty,++	MRF604, 2SC2053
40406(L,S)	Si-P	NF-Tr,-/50V, 0,7A, 1W, 100MHz	2a	Rca,Sty,++	BC161, BC303..304, 2SA606
40407(L,S)	Si-N	NF-Tr,-/50V, 0,7A, 1W, 100MHz	2a	Rca,Sty,++	BC140..141, BC300..302, 2N3053,,++

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40408(L,S)	Si-N	NF-Tr,-/90V,0,7A,1W,100MHz	2a	Rca,Sty,++	BC141,BC300..301,2N1990,2N2405,++
40409	Si-N	NF-Tr/E,90V,0,7A,3W(Ta=50°)	2a°	Rca,Sty,++	BD139,BD230,BD529,BD829,++)
4041	CMOS-Logic	Quad True/Complement Buffer	14-DIP		—
4041	CMOS-Logic		20-MP		—
40410	Si-P	NF-Tr/E,90V,0,7A,3W(Ta=50°)	2a°	Rca,Sty,++	(BD140,BD231,BD530,BD830,++)
40411	Si-N	NF-L,90V,30A,150W,0,8MHz	23a	Rca,Sty,++	BDW30,BDY29,MJ802,2SD797
40412(L,S)	Si-N	NF/S,-/250V,1A,10W(Tc=25°),>10MHz	2a	Rca,Sty,++	BUX55,BUY59..60,2N5092,2N5095,++
40412V1	Si-N	=40412:4W	2a°		(BD410,BUW40(A,B),TIP47..50,++)
40412V2	Si-N	=40412:4W	43m		(BD410,BUW40(A,B),TIP47..50,++)
40413	Si-N	UHF,>700MHz	5g	Rca	BF377..378,BF689,BF763,2N2857,++
40414	Si-N	UHF,>1000MHz	5g	Rca	BF377..378,BF689,BF763,2N2857,++
4042	CMOS-Logic	Quad D-Latch with Common Enable and	16-DIP		—
4042	CMOS-Logic	Complementary Outputs	20-MP		—
40421	Ge-P	NF-L,75V,5A,12,5W(Tc=80°)	23a	Gpd,Rca	AL102..103,AUY28,2N1541..43,++
40422	Si-N	NF/Vid-L,300V,0,15A,8W(Tc=75°)	22a	Rca,Sca,Sty	2SC1505..1507,2SC1755..1757,2SC1905,++
40423	Si-N	=40422:	22a°	Rca,Sca,Sty	2SC1505..1507,2SC1755..1757,2SC1905,++
40424	Si-N	NF/Vid-L,300V,0,15A,8W(Tc=75°)	22a	Rca,Sca,Sty	2SC1505..1507,2SC1755..1757,2SC1905,++
40425	Si-N	=40424:	22a°	Rca,Sca,Sty	2SC1505..1507,2SC1755..1757,2SC1905,++
40428	Si-N	NF/Vid-L,300V,0,15A,8W(Tc=75°)	22a	Rca,Sca,Sty	2SC1505..1507,2SC1755..1757,2SC1905,++
40427	Si-N	=40426:	22a°	Rca,Sca,Sty	2SC1505..1507,2SC1755..1757,2SC1905++
40428	Ge-Di	Stabi,0,275V(80mA)	2c	Rca	—
40429	Triac	=T2700B	22m	Rca	→T2700B
4043	CMOS-Logic	Quad NOR RS Flip-Flop	16-DIP		—
4043	CMOS-Logic		20-MP		—
40430	Triac	=T2700D	22m	Rca	→T2700D
40431	Triac	+Diac,200V,6A,Ih<30mA	2m	Rca	—
40432	Triac	=40431:400V	2m	Rca	—
40439	Ge-P	TV-HA,320V,10A,5W(Tc=55°)	23a	Gpd,Rca	AU108,AU109,AU111..112,2N5325
4044	CMOS-Logic	Quad NAND RS Flip-Flope	16-DIP		—
4044	CMOS-Logic		20-MP		—
40440	Ge-P	TV-HA,200V,10A,5W(Tc=55°)	23a	Gpd,Rca	AU107,AU113,AU213,2N5324
40442	Ge-Di	TV-Damper-Di,200V,7A	23	Rca	—
40444	Si-N	HF-L,120/60V,20A,PQ>20W(2,5MHz)	23a	Rca,Sca	—
40446	Si-N	AM-L,-/60V,1,5A,PQ>3W(27MHz)	43m	Rca,Sca,Sty	(2SC2020,2SC2029)
4045	CMOS-Logic	Asynchronous Binary 21-Bit Up Counter	16-DIP		—
4045	CMOS-Logic		20-MP		—
40450	Si-N	=2N3241A:1W	2a°	Rca,Sty	→2N3241A
40451	Si-N	=2N3242A:1W	2a°	Rca,Sty	→2N3242A
40452	Si-N	=2N4074:1W	2a°	Rca,Sty	→2N4074
40453	Si-N	=40397:1W	2a°	Rca,Sty	→40397
40454	Si-N	=40398:1W	2a°	Rca,Sty	→40398
40455	Si-N	=40399:1W	2a°	Rca,Sty	→40399
40456	Si-N	=40400:1W	2a°	Rca,Sty	→40400
40457	Si-N	Uni,25V,1A,0,5W,>80MHz	2a	Sca	BC337..338,BC635,BC637,BC639,++
40456	Si-N	Uni/S,80V,1A,0,5W,<75/575ns	2a	Rca,Sca,Sty	BC637,BC639,BSS26,BSS40..41,++
40459	Si-N	=40458:1W	2a°	Rca,Sty	BC637,BC639,BSS28,BSS40..41,++
4046	CMOS-Logic	Phase-Locked-Loop Switcher(PLL)	16-DIP		—
4046	CMOS-Logic		20-MP		—
40460	MOS-N-FET-d	NF/HF/S,25V,Idss<9mA	5n	Rca	—
40481	MOS-N-FET-d	NF/HF/S,25V,Idss=4..14mA	5n	Rca	—
40462	Ge-P	NF/S-L,40V,5A,12,W(Tc=75°)	23a	Gpd,Rca,Sty	AL102..103,AUY28,2N1539..48,++
40484	Si-N	NF/S-L,35V,5A,40W,>2MHz	23a	Rca,Sea	BD245,BDV91,BDX91,2N4914..15,++
40485	Si-N	=40464:40V	23a	Rca,Sea	BD245,BDV91,BDX91,2N4914..15,++
40466	Si-N	=40464:50V	23a	Rca,Sea	BD245,BDV91,BDX91,2N4914..15,++
40487(A)	MOS-N-FET-d	VHF-V,20V,Idss>10mA,Up<8V	5m	Rca	—
40468(A)	MOS-N-FET-d	AM/FM-V,20V,Idss>5mA	5m	Rca	—
40469	Si-N	VHF,re,700MHz	5k	Rca,Sty	BF225,BF314,BF502,BF505,BF506++
4047	CMOS-Logic	Monostable/Astable Multivibrator	14-DIP		—
4047	CMOS-Logic		20-MP		—
40470	Si-N	TV-ZF,re,700MHz	5k	Rca,Sty	BF198,BF225,BF310,BF367,BF596++
40471	Si-N	TV-ZF,re,700MHz	5k	Rca,Sty	BF198,BF225,BF310,BF367,BF596++
40472	Si-N	VHF-V,900MHz	5k	Nsc,Rca,Sca	BF225,BF314,BF502,BF505,BF507++
40473	Si-N	VHF-M,900MHz	5k	Nsc,Rca,Sca	BF224,BF314,BF503,BF505,BF507++
40474	Si-N	VHF-O,900MHz	5k	Nsc,Rca,Sca	BF224,BF314,BF503,BF505,BF507++
40475	Si-N	TV-ZF,800MHz	5k	Nsc,Rca,Sca	BF199,BF224,BF311,BF373,BF597++
40476	Si-N	TV-ZF,800MHz	5k	Nsc,Rca,Sca	BF199,BF224,BF311,BF373,BF597++

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40477	Si-N	TV-ZF, 800MHz	5k	Nsc,Rca,Sca	BF199, BF224, BF311, BF373, BF597++
40478	Si-N	FM-V, 800MHz	5k	Nsc,Rca,Sca	BF241, BF255, BF495, BF595,++
40479	Si-N	FM-M, 800MHz	5k	Nsc,Rca,Sca	BF241, BF255, BF495, BF595,++
4048	CMOS-Logic	8-Input Multifunction-Gate	18-DIP		—
4048	CMOS-Logic		20-MP		—
40480	Si-N	FM-O, 800MHz	5k	Nsc,Rca,Sca	BF240, BF254, BF494, BF594,++
40481	Si-N	FM-ZF, 860MHz	5k	Nsc,Rca,Sca	BF240, BF254, BF494, BF594,++
40482	Si-N	FM-ZF, 860MHz	5k	Nsc,Rca,Sca	BF240, BF254, BF494, BF594,++
40485	Triac	200V, 6A, Igt/Ih<40/<30mA	2m	Rca	—
40486	Triac	=40485 400V	2m	Rca	—
40487	Ge-P	AM-M, 40MHz	2a	Rca,Sty	AF124..127, AF200
40488	Ge-P	AM-O, 30MHz	2a	Rca,Sty	AF124..127, AF200
40489	Ge-P	AM-ZF, 30MHz	2a	Rca,Sty	AF124..127, AF200
4049	CMOS-Logic	Hex Inverter/Buffer	16-DIP		—
4049	CMOS-Logic		20-MP		—
40490	Ge-P	NF, 20V, 0,02A, 0,12W	2a	Rca,Sty	AC125..126, AC151
40491	Si-N	NF-E, 300V, 0,15A, 3,8W, 25MHz	22a°	Rca,Sty,++	2SC1505..1507, 2SC1755..1757, 2SC1905
40495	Si-Di	Gl, 400V, 0,5A	34	Rca	BY126..127, BY133..134, 1N4004..07,++
4050	CMOS-Logic	TTL Driver, non inverting	16-DIP		—
4050	CMOS-Logic		20-MP		—
40500	Si-N	Uni, 30V, 0,2A, 0,5W, >80MHz	2a	Sce	BC168, BC183, BC238, BC548,++
40502	Triac	=T2710B	22m°	Rca	→T2710B
40503	Triac	=T2710D	22m°	Rca	→T2710D
40504	50Hz-Thy	=S2710B	22a°	Rca	→S2710B
40505	50Hz-Thy	=S2710D	22a°	Rca	→S2710D
40506	50Hz-Thy	=S2710M	22a°	Rca	→S2710M
40507	50Hz-Thy	=S2600B	2a°	Rca	→S2600B
40508	50Hz-Thy	=S2600D	2a°	Rca	→S2600D
40509	Triac	=40485	2m°	Rca	→40485
4051	CMOS-Logic	8-Channel Multiplexer, Analog/Digital	16-DIP		—
4051	CMOS-Logic		20-MP		—
40510	Triac	=40486	2m°	Rca	→40486
40511	Triac	=40431	2m°	Rca	→40431
40512	Triac	=40432	2m°	Rca	→40432
40513	Si-N	NF/S-L, 45V, 6A, 83W, >0,8MHz		Rca	BD245, BDV91, 2SD895..896
40514	Si-N	=40513		Rca	BD245, BDV91, 2SD895..896
40517	Si-N	UHF, ra, 1900MHz	5g	Rca,Sty	BF377..378, BF689, BF783, 2SC2570,++
40518	Si-N	=40517: hi-rel	5g	Rca,Sty	(BF377..378, BF689, BF783, 2SC2570++)
40519	Si-N	VHF/UHF-Tr, 40V, 0,5A, PQ=0,3W(240MHz)	2a	Rca,Ssi,Sty	(BFS50, MRF515, 2SC2652)
4052	CMOS-Logic	Dual 4-Channel Multiplexer,	16-DIP		—
4052	CMOS-Logic	Analog/Digital	20-MP		—
40525	Triac	=T2300A	2m	Rca	→T2300A
40526	Triac	=T2300B	2m	Rca	→T2300B
40527	Triac	=T2300D	2m	Rca	→T2300D
40528	Triac	=TC24062302A	2m	Rca	→T2302A
40529	Triac	=T2302B	2m	Rca	→T2302B
4053	CMOS-Logic	Triple 2-Channel Multiplexer,	16-DIP		—
4053	CMOS-Logic	Analog/Digital	20-MP		—
40530	Triac	=T2302D	2m	Rca	→T2302D
40531	Triac	=T2310A	2m°	Rca	→T2310A
40532	Triac	=T2310B	2m°	Rca	→T2310B
40533	Triac	=T2310D	2m°	Rca	→T2310D
40534	Triac	=T2312A	2m°	Rca	→T2312A
40535	Triac	=T2312B	2m°	Rca	→T2312B
40536	Triac	=T2312D	2m°	Rca	→T2312D
40537(L,S)	Si-P	NF-Tr, 55V, 0,7A, 1W, 100MHz	2a	Rca,Sty,++	BC161, BC303..304, 2SA606
40538(L,S)	Si-P	NF-Tr, 55V, 0,7A, 1W, 100MHz	2a	Rca,Sty,++	BC161, BC303..304, 2SA606
40539(L,S)	Si-N	NF-Tr, 55V, 0,7A, 1W, 100MHz	2a	Rca,Sty,++	BC140..141, BC300..302, 2N1990,++
4054	CMOS-Logic	4-Segment Liquid-Crystal Display	16-DIP		—
4054	CMOS-Logic	Driver	20-MP		—
40542	Si-N	NF-L, 50V, 6A, 83W, >0,8MHz		Rca	BD245, BDV91, 2SD718, 2SD895..896,++
40543	Si-N	NF-L, 80V, 6A, 83W, >0,8MHz		Rca	BD245A, BDV91, 2SC3256, 2SD718,++
40544	Si-N	NF-Tr/E, 50V, 0,7A, 7W, 100MHz	43m	Rca,Sty,++	(BD137, BD228, BD525, BD827,++)
40546	Si-N	NF-L, 250V, 0,15A, 8W(Tc=75°), B>50	22a	Rca,Sty	2SC1505..1507, 2SC1755..1757, 2SC1905
40547	Si-N	=40546: B>20	22a	Rca,Sty	2SC1505..1507, 2SC1755..1757, 2SC1905
4055	CMOS-Logic	BCD-to-7-Segment Decoder C15811	16-DIP		—

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4055	CMOS-Logic	LCD-Displays	20-MP		—
40553	F-Thy	=S3700B	22a	Rca	→S3700B
40554	F-Thy	=S3700D	22a	Rca	→S3700D
40555	F-Thy	=S3700M	22a	Rca	→S3700M
40559(A)	MOS-N-FET-d	AM/FM-M, 20V, Idss>5mA, Up<6V	5m	Rca	—
4056	CMOS-Logic	BCD-to-7-Segment	16-DIP		—
4056	CMOS-Logic	Decoder/Memory/Driver for LCD-Displays	20-MP		—
40561	Ge-Di	=1N3847	≈34	Rca	→1N3847
40562	Ge-Di	=1N3848	≈34	Rca	→1N3848
40563	Ge-Di	=1N3849	≈34	Rca	→1N3849
40564	Ge-Di	=1N3850	≈34	Rca	→1N3850
40565	Ge-Di	=1N3851	≈34	Rca	→1N3851
40566	Ge-Di	=1N3852	≈34	Rca	→1N3852
40567	Ge-Di	=1N3853	≈34	Rca	→1N3853
40568	Ge-Di	=1N3854	≈34	Rca	→1N3854
40569	Ge-Di	=1N3855	≈34	Rca	→1N3855
40570	Ge-Di	=1N3856	≈34	Rca	→1N3856
40571	Ge-Di	=1N3857	≈34	Rca	→1N3857
40572	Ge-Di	=1N3856	≈34	Rca	→1N3856
40573	Ge-Di	=1N3859	≈34	Rca	→1N3859
40574	Ge-Di	=1N3860	≈34	Rca	→1N3860
40575	Triac	=T4700B	22m	Rca	→T4700B
40576	Triac	=T4700D	22m	Rca	→T4700D
40577	Si-N	=2N3118: hi-rel	2a	Rca, Ssi	→2N3118
40578	Si-N	=2N3866: hi-rel	2a	Rca, Sty	→2N3866
40581	Si-N	AM-Tr/E, 60V, 1,5A, PQ>3,5W(27MHz)	2a	Rca, Sca	(2SC2020, 2SC2029)
40562	Si-N	AM-L, 60V, 1,5A, PQ>3,5W(27MHz)	43m	Rca, Sca	(2SC2020, 2SC2029)
40583	Diac	Ub=27..37, Ib<0,05mA, Itsm=2A	31	Rca	1N5761, N413M, BR100, D3202Y, D0201YR
4059	CMOS-Logic	16-Bit Programmable Divider	24-DIP		—
40594(L,S)	Si-N	=RCA1A03	2a	Rca, Sca, Sty	→RCA1A03
40595(L,S)	Si-P	=RCA1A04	2a	Rca, Sca, Sty	→RCA1A04
4060	CMOS-Logic	Asynchronous Binary 14-Bit Up Counter	16-DIP		—
4060	CMOS-Logic	with Internal Oscillator	20-MP		—
40600	MOS-N-FET-d	Dual-Gate, VHF, 20V, Idss=18mA, Up=2V	5h	Rca	BF351..353, 3N201..206, 3N211..213,++
40601	MOS-N-FET-d	Dual-Gate, VHF, 20V, Idss=18mA, Up=2V	5h	Rca	BF351..353, 3N201..206, 3N211..213,++
40602	MOS-N-FET-d	Dual-Gate, TV-ZF, 20V, Idss=18mA, Up=2V	5h	Rca	BF351..353, 3N201..206, 3N211..213,++
40603	MOS-N-FET-d	Dual-Gate, FM-V, 20V, Idss=18mA, Up=2V	5h	Rca	BF351..353, 3N201..206, 3N211..213,++
40604	MOS-N-FET-d	Dual-Gate, FM-M, 20V, Idss=18mA, Up=2V	5h	Rca	BF351..353, 3N201..206, 3N211..213,++
40605	Si-N	VHF/UHF-E, 65V, 0,33A, PQ>1,5W(500MHz)	2a	Rca, Ssi	BFR97, 2SC2852
40606	Si-N	VHF-A, 40V, 0,4A, >700MHz	2a	Rca, Ssi	BFS50, MRF629, 2N3948, 2SC2852, ++
40611(L,S)	Si-N	NF-Tr, -/25V, 0,7A, 1W, 100MHz	2a	Rca, Sty,++	BC140..141, BC300..302, 2N3053,++
40612	Ge-P	NF-L, 25V, 5A, 12,5W	23a	Gpd, Rca, Sty	AL102..103, AUY28, 2N1529..48,++
40613	Si-N	NF-L, -/25V, 4A, 36W	17j	Rca, Sty,++	BD243, BD533, BD539, BD947, ++
40618(L,S)	Si-N	NF-Tr, -/32V, 0,7A, 1W, 100MHz	2a	Rca, Sty	BC140..141, BC300..302, 2N3053,++
40618	Si-N	NF-L, -/30V, 4A, 38W, >0,8MHz	17j	Rca, Ssi, Sty	BD243, BD533, BD539, BD947, ++
4062	CMOS-Logic	200-Bit Dynamic Serial Shift Register	16-DIP		—
40621	Si-N	NF-L, -/32V, 4A, 38W, >0,8MHz	17j	Rca, Ssi, Sty	BD243, BD533, BD539, BD947, ++
40622	Si-N	=40621: -/40V	17j	Rca, Ssi, Sty	BD243, BD533, BD539, BD947, ++
40623	Ge-P	NF-L, 45V, 5A, 12,5W	23a	Gpd, Rca, Sty	AL102..103, AUY28, 2N1529..48,++
40624	Si-N	NF-L, -/45V, 6A, 50W	17j	Rca, Ssi, Sty	BD243A, BD543A, BD797, BD607, ++
40625	Si-N	NF-Tr/E, -/45, 1A, 3,5W	2a°	Rca, Ssi, Sty	(BD137, BD228, BD525, BD627,++)
40626	Ga-P	NF-L, 55V, 5A, 12,5W	23a	Gpd, Rcs, Sty	AL102..103, AUY28, 2N1540..48,++
40627	Si-N	NF-L, -/55V, 6A, 50W	17j	Rca, Ssi	BD243B, BD543B, BD799, BD809, ++
40628	Si-N	NF-Tr/E, -/55V, 1A, 3,5W	2a°	Rca, Ssi, Sty	(BD139, BD230, BD527, BD829,++)
40629	Si-N	NF-L, 35V, 4A, 38W	17j	Rca, Ssi	BD243, BD533, BD539, BD947, ++
4063	CMOS-Logic	4-Bit Comparator	16-DIP		—
4063	CMOS-Logic		20-MP		—
40630	Si-N	NF-L, 40V, 4A, 36W	17j	Rca, Ssi	BD243, BD533, BD539, BD947, ++
40631	Si-N	NF-L, 45V, 4A, 38W	17j	Rca, Ssi	BD243, BD533, BD539A, BD947, ++
40632	Si-N	NF-L, 60V, 6A, 50W	17j	Rca, Ssi	BD243A, BD543A, BD797, BD607, ++
40633	Si-N	NF-L, 75V, 6A, 83W		Rca, Sty	BD245B, BD545B, BDV93, 2SD718,++
40634(L,S)	Si-P	=RCA1A05	2a	Rca, Sty,++	→RCA1A05
40635(L,S)	Si-N	=RCA1A06	2a	Rca, Sty,++	→RCA1A06
40636	Si-N	=RCA1B01	23a	Rca, Sty,++	→RCA1B01
40637	Si-N	VHF-Tr, 30V, 0,1A, 0,3W, 300MHz	2a	Rca, Ssi, Sty	BFX59
40637A	Si-N	=40637: 36V, 0,2A, 0,75W	2a		2SC2053, 2SC2851, (BFR36)

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40638	Triac	=40485	2m°	Rca	→40485
40639	Triac	=40486	2m°	Rca	→40486
40640	F-Thy	=S 3705M	22a	Rca	→S 3705M
40641	F-Thy	=S 3706M	22a	Rca	→S 3706M
40642	Si-Di	=D 2601EF	31a	Rca	→D2601EF
40643	Si-Di	=D 2601DF	31a	Rca	→D2601DF
40644	Si-Di	=D 2600EF	31a	Rca	→D2600EF
40654	50Hz-Thy	=S 2600B	2a	Rca	→S 2600B
40655	50Hz-Thy	=S 2600D	2a	Rca	→S 2600D
40656	50Hz-Thy	=S 2620B	2a°	Rca	→S 2620B
40657	50Hz-Thy	=S 2620D	2a°	Rca	→S 2620D
40656	50Hz-Thy	=S 2610B	2a°	Rca	→S 2610B
40659	50Hz-Thy	=S 2610D	2a°	Rca	→S 2610D
4066	CMOS-Logic	Quad Bilateral Digital or Analog	14-DIP		—
4066	CMOS-Logic	Switch (4x1 Closer)	20-MP		—
40660	Triac	=T 6401B	29l	Rca	→T6401B
40661	Triac	=T 6401D	29l	Rca	→T6401D
40662	Triac	=T 6411B	21l	Rca	→T8411B
40663	Triac	=T 6411D	21l	Rca	→T6411D
40664	Triac	450V, 6A, Igt<50mA	2m	Rca	—
40665	Si-N	VHF/UHF-L, 65V, 1A, PQ>13,5W(175MHz)	49a	Rca,Ssi,Sty	BLY 60, 2N3632
40666	Si-N	VHF/UHF-L, 66V, 0,5A, PQ>3W(400MHz)	49a	Rca,Ssi,Sty	(BLY 60, 2N3632)
40667	Triac	=40664	2m°	Rca	—
40668	Triac	=T 2800B	17j	Rca	→T2600B
40668	Triac	=T 2600D	17j	Rca	→T2600D
4067	CMOS-Logic	16-Channel Multiplexer/Demultiplexer,	24-DIP		—
4067	CMOS-Logic	analog/digital			—
40670	Triac	=T 2800M	17j	Rca	→T2800M
40671	Triac	=T 6401M	29l	Rca	→T6401M
40672	Triac	=T 6411M	21l	Rca	→T6411M
40673	MOS-N-FET-d	Dual-Gate, VHF/UHF, 20V, Idss>5mA, Up<4V	5h	Rca	3N209. 210
40675	Si-N	AM-L(SSB), +Stabi-Diode, 65V, 10A		Rca	—
4068	CMOS-Logic	8-Input NAND Gate	14-DIP		—
4068	CMOS-Logic		20-MP		—
40680	Triac	=S 6420A	54l	Rca	→S 6420A
40681	Triac	=S 6420B	54l	Rca	→S 6420B
40682	Triac	=S 6420D	54l	Rca	→S6420D
40683	Triac	=S 6420M	54l	Rca	→S6420M
40684	Triac	=T 2313A	2m°	Rca	→T2313A
40685	Triac	=T 2313B	2m°	Rca	→T2313B
40686	Triac	=T 2313D	2m°	Rca	→T2313D
40687	Triac	=T 2313M	2m°	Rca	→T2313M
40686	Triac	=T 8420B	54l	Rca	→T6420B
40689	Triac	=T 6420D	54l	Rca	→T6420D
4069	CMOS-Logic	Hex Inverter	14-DIP		—
4069	CMOS-Logic		20-MP		—
40690	Triac	=T 6420M	54l	Rca	→T6420M
40691	Triac	=T 2301B	2m	Rca	→T2301B
40692	Triac	=T 2301D	2m	Rca	→T2301D
40693	Triac	=T 2316A	2m°	Rca	→T2316A
40694	Triac	=T 2316B	2m°	Rca	→T2316B
40695	Triac	=T 2316D	2m°	Rca	→T2316D
40696	Triac	=T 2306A	2m	Rca	→T2306A
40697	Triac	=T 2306B	2m	Rca	→T2306B
40696	Triac	=T 2306D	2m	Rca	→T2306D
40699	Triac	=T 6406B	29l	Rca	→T6406B
4070	CMOS-Logic	Quad 2-Input EX-OR Gate	14-DIP		—
4070	CMOS-Logic		20-MP		—
40700	Triac	=T 6406D	29l	Rca	→T6406D
40701	Triac	=T 6406M	29l	Rca	→T6406M
40702	Triac	=T 6416B	21l	Rca	→T6416B
40703	Triac	=T 6416D	21l	Rca	→T6416D
40704	Triac	=T 6418M	21l	Rca	→T6416M
40705	Triac	=T 6407B	29l	Rca	→T6407B
40706	Triac	=T 6407D	29l	Rca	→T6407D
40707	Triac	=T 6417B	21l	Rca	→T6417B

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40708	Triac	=T6417D	21l	Rca	→T6417D
40708	Triac	=T6407M	29l	Rca	→T6407M
4071	CMOS-Logic	Quad 2-Input OR Gate	14-DIP		—
4071	CMOS-Logic		20-MP		—
40710	Triac	=T6407M	29l	Rca	→T6407M
40711	Triac	=T4106B	29l	Rca	→T4106B
40712	Triac	=T4108D	29l	Rca	→T4106D
40713	Triac	=T4116B	21l	Rca	→T4116B
40714	Triac	=T4116D	21l	Rca	→T4116D
40715	Triac	=T4708B	22m	Rca	→T4708B
40716	Triac	=T4706D	22m	Rca	→T4708D
40717	Triac	=T4107B	29l	Rca	→T4107B
40718	Triac	=T4107D	29l	Rca	→T4107D
40719	Triac	=T4117B	21l	Rca	→T4117B
4072	CMOS-Logic	Dual 4-Input OR Gate	14-DIP		—
4072	CMOS-Logic		20-MP		—
40720	Triac	=T4117D	21l	Rca	→T4117D
40721	Triac	=T2806B	17j	Rca	→T2806B
40722	Triac	=T2808D	17j	Rca	→T2808D
40723	Triac	=T2606DF	2m	Rca	→T2806DF
40724	Triac	=T2816DF	2m*	Rca	→T2616DF
40725	Triac	=T2606B	2m	Rca	→T2806B
40726	Triac	=T2606D	2m	Rca	→T2606D
40727	Triac	=T2708B	22m	Rca	→T2706B
40728	Triac	=T2708D	22m	Rca	→T2708D
40729	Triac	=T2716B	22m*	Rca	→T2716B
4073	CMOS-Logic	Triple 3-Input AND Gate	14-DIP		—
4073	CMOS-Logic		20-MP		—
40730	Triac	=T2716D	22m*	Rca	→T2716D
40731	Triac	=40485: Igt/Ih<45/15mA	2m*	Rca	—
40732	Triac	=40486; Igt/Ih<45/15mA	2m*	Rca	—
40733	Triac	=40485: Igt/Ih<45/15mA	2m*	Rca	—
40734	Triac	=40486: Igt/Ih<45/15mA	2m*	Rca	—
40735	F-Thy	=2N3653: 600V, =S7430M	21l	Rca	→S7430M, 2N3653
40737	50Hz-Thy	100V, 6,3A(Tc=85°C), Igt/Ih<15/<20mA	29b	Rca	T6N100H, T8N100H, BStD4026, S6200A, ++
40738	50Hz-Thy	=40737: 200V	29b		T6N200H, T8N200H, BStD4026, S6200B, ++
40739	50Hz-Thy	=40737: 400V	29b	Rca	T8N400H, T8N400H, BStD4026, S6200D, ++
40740	50Hz-Thy	=40737: 600V	29b	Rca	T6N600H, T8N600H, BStD4040, S6200M, ++
40741	50Hz-Thy	=40737:	21b		T6N100C, T8N100C, BStD4126, S6210A, ++
40742	50Hz-Thy	=40739:	21b		T6N200C, T8N200C, BStD4126, S6210B, ++
40743	50Hz-Thy	=40739:	21b		T6N400C, T8N400C, BStD4128, S6210D, ++
40744	50Hz-Thy	=40740:	21b		T8N600C, T8N600C, BStD4140, S6210M, ++
40745	50Hz-Thy	=40737: Iso	54b		S6220A, C230A3
40748	50Hz-Thy	=40738: Iso	54b		S6220B, C230B3
40747	50Hz-Thy	=40739: Iso	54b		S6220D, C230D3
40748	50Hz-Thy	=40740: Iso	54b		S6220M, C230M3
40749	50Hz-Thy	=S6200A	29b	Rca	→S6200A
4075	CMOS-Logic	Triple 3-Input OR Gate	14-DIP		—
4075	CMOS-Logic		20-MP		—
40750	50Hz-Thy	=S6200B	29b	Rca	→S6200B
40751	50Hz-Thy	=S6200D	29b	Rca	→S6200D
40752	50Hz-Thy	=S6200M	29b	Rca	→S6200M
40753	50Hz-Thy	=S6210A:	21b		→S6210A
40754	50Hz-Thy	=S6210B:	21b		→S6210B
40755	50Hz-Thy	=S6210D:	21b		→S6210D
40756	50Hz-Thy	=S6210M:	21b		→S6210M
40757	50Hz-Thy	=S6220A: Iso	54b		→S6220A
40758	50Hz-Thy	=S6220B: Iso	54b		→S6220B
40759	50Hz-Thy	=S6220D: Iso	54b		→S6220D
4076	CMOS-Logic	Dual 2-Bit D-Latch	16-DIP		—
4076	CMOS-Logic		20-MP		—
40760	50Hz-Thy	=S6220M: Iso	54b		→S6220M
40761	Triac	=T2311B	2m*	Rca	→T2311B
40762	Triac	=T2311D	2m*	Rca	→T2311D
40766	Triac	=T2301A	2m	Rca	→T2301A
40767	Triac	=T2311A	2m*	Rca	→T2311A

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40768	F-Thy	=S3701M	22a	Rca	→S3701M
40769	Triac	=T2304B	2m	Rca	→T2304B
4077	CMOS-Logic	Quad 2-Input EX-NOR Gate	14-DIP		—
4077	CMOS-Logic		20-MP		—
40770	Triac	=T2304D	2m	Rca	→T2304D
40771	Triac	=T2305B	2m	Rca	→T2305B
40772	Triac	=T2305D	2m	Rca	→T2305D
40773	Triac	200V, 2,5A, Igt/Ih<40/<30mA	2m	Rca	T2306B, T2303B, TAG208-200
40774	Triac	=40773: 400V	2m	Rca	T2306D, T2303D, TAG208-400
40775	Triac	=T4105B	29l	Rca	→T4105B
40776	Triac	=T4105D	29l	Rca	→T4105D
40777	Triac	=T4115B	21l	Rca	→T4115B
40778	Triac	=T4115D	21l	Rca	→T4115D
40779	Triac	=T4104B	29l	Rca	→T4104B
4078	CMOS-Logic	8-Input NOR/OR Gate	14-DIP		—
4078	CMOS-Logic		20-MP		—
40780	Triac	=T4104D	29l	Rca	→T4104D
40781	Triac	=T4114B	21l	Rca	→T4114B
40782	Triac	=T4114D	21l	Rca	→T4114D
40783	Triac	=T4103B	29l	Rca	→T4103B
40784	Triac	=T4103D	29l	Rca	→T4103D
40785	Triac	=T4113B	21l	Rca	→T4113B
40786	Triac	=T4113D	21l	Rca	→T4113D
40787	Triac	=T6405B	29l	Rca	→T6405B
40788	Triac	=T8405D	29l	Rca	→T8405D
40789	Triac	=T6415B	21l	Rca	→T6415B
40790	Triac	=T8415D	21l	Rca	→T8415D
40791	Triac	=T6404B	29l	Rca	→T6404B
40792	Triac	=T8404D	29l	Rca	→T6404D
40793	Triac	=T6414B	21l	Rca	→T6414B
40794	Triac	=T8414D	21l	Rca	→T6414D
40795	Triac	=T4101M	29l	Rca	→T4101M
40796	Triac	=T4111M	21l	Rca	→T4111M
40797	Triac	=T4100M	29l	Rca	→T4100M
40798	Triac	=T4110M	21l	Rca	→T4110M
40789	Triac	=T4121B: Iso	54l	Rca	→T4121B
40800	Triac	=T4121D: Iso	54l	Rca	→T4121D
40801	Triac	=T4121M: Iso	54l	Rca	→T4121M
40802	Triac	=T4120B: Iso	54l	Rca	→T4120B
40803	Triac	=T4120D: Iso	54l	Rca	→T4120D
40804	Triac	=T4120M	54l	Rca	→T4120M
40805	Triac	=T6421B: Iso	54l	Rca	→T6421B
40808	Triac	=T6421D: Iso	54l	Rca	→T8421D
40807	Triac	=T6421M: Iso	54l	Rca	→T6421M
40808	Si-Di	Gl, contr av., 600V, 0,5A	31a	Rca	BTV36C, BTV95C, BTW95C, 1N4247..49,++
40809	Si-Di	=40808: 800V	31a	Rca	BTV36D, BTV96D, BTW96D, 1N4246..49,++
40809	Ga-N/P	=AC127+AC128	2a	Rca	→AC127/128
4081	CMOS-Logic	Dual 4-Input AND Gate	14-DIP		—
4081	CMOS-Logic		20-MP		—
40810	50Hz-Thy	100V, 1,5A(Tc=75°C), Igt/Ih<15/<20mA	2a	Rca	TAG612-100, TAG613-100, TAG606-100,++
40811	50Hz-Thy	=40810: 200V	2a		TAG612-200, TAG613-200, TAG606-200,++
40812	50Hz-Thy	=40810: 400V	2a		TAG612-400, TAG613-400, TAG608-400,++
40813	50Hz-Thy	=40810: 600V	2a		TAG612-600, TAG613-800, TAG606-600,++
40814	Si-N	=RCA1A07	2a	Rca	→RCA1A07
40815	Si-P	=RCA1A08	2a	Rca	→RCA1A08
40819	MOS-N-FET-d	Dual-Gate, VHF-V, 25V, Idss>5mA, Up<4V	5h	Rca	BF351, 3N201..206, 3N211..213
4082	CMOS-Logic	Quad 2-Input AND Gate	14-DIP		—
4082	CMOS-Logic		20-MP		—
40820	MOS-N-FET-d	Dual-Gate, VHF-V, 20V, Idss>0,5mA, Up<3V	5h	Rca	3SK68, 3SK79, 3SK87, 3SK100
40821	MOS-N-FET-d	Dual-Gate, VHF-M, 20V, Idss>0,5mA, Up<3V	5h	Rca	3SK66, 3SK79, 3SK87, 3SK100
40822	MOS-N-FET-d	Dual-Gate, FM-V, 20V, Idss>5mA, Up<4V	5h	Rca	BF351, 3N201..206, 3N211..213
40823	MOS-N-FET-d	Dual-Gate, FM-M, 20V, Idss>5mA, Up<4V	5h	Rca	BF351, 3N201..206, 3N211..213
40829	Si-P	=2N5954; 58W	22a°	Rca	→2N5954
40830	Si-P	=2N5955: 58W	22a°	Rca	→2N5955
40831	Si-P	=2N5956: 58W	22a°	Rca	→2N5956
40832	Si-N	=40852	23a	Rca	→40852

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40833	50Hz-Thy	=S2600M	2a	Rca	→S2600M
40834	50Hz-Thy	=S2620M	2a°	Rca	→S2620M
40835	50Hz-Thy	=S2610M	2a°	Rca	→S2610M
40836	Si-N	UHF-O, 50V, 0,2A, PQ=0,65W(2GHz)	Koax	Rca	—
40837	Si-N	UHF-O, 50V, 0,275A, PQ=1,35W(2GHz)	Koax	Rca	—
40841	MOS-N-FET-d	Dual-Gate, VHF, 24V, Idss=10mA, Up=2V	5h	Rca	BF351, 3N201..206, 3N211..213
40842	Triac	=T2801DF	17j	Rca	→T2801DF
4085	CMOS-Logic	Dual AND/NOR Combination-Gate with	14-DIP		—
4085	CMOS-Logic	2x2 Inputs	20-MP		—
40850	Si-N	≈2N3585	22a	Rca, Sty, ++	→2N3585
40851	Si-N	≈2N6079	22a	Rca, Sty, ++	→2N6079
40852	Si-N	≈2N5240	23a	Rca, Sty, ++	→2N5240
40853	Si-N	≈2N5805	23a	Rca, Sty, ++	→2N5805
40854	Si-N	=2N6251	23a	Rca, Sty, ++	→2N6251
4086	CMOS-Logic	Dual 2x2-Input AND/NOR	14-DIP		—
4086	CMOS-Logic	Combination-Gate, expandable	20-MP		—
40867	50Hz-Thy	=S2800A	17e	Rca	→S2800A
40868	50Hz-Thy	=S2800B	17e	Rca	→S2800B
40869	50Hz-Thy	=S2800D	17e	Rca	→S2800D
40871	Si-N	NF/S-L, 120V, 7A, 40W, >4MHz	17j	Rca	BD243D, BD543D, 2SD550, 2SD866
40872	Si-P	NF/S-L, 120V, 7A, 40W, >4MHz	17j	Rca	BD244D, BD544D, 2SB870
40873	Si-N	NF/S-L, 80V, 7A, 40W, >4MHz	17j	Rca	BD243B, BD543B, BD799, BD809, ++
40874	Si-P	NF/S-L, 60V, 7A, 40W, >4MHz	17j	Rca	BD244D, BD544D, BD800, BD810, ++
40875	Si-N	NF/S-L, 60V, 7A, 40W, >4MHz	17j	Rca	BD243A, BD543A, BD797, BD807, ++
40876	Si-P	NF/S-L, 60V, 7A, 40W, >4MHz	17j	Rca	BD244A, BD544A, BD798, BD808, ++
40877	Si-N	NF/S-L, -/65V, 10A, 75W, 7MHz	17j	Rca	BD709, BD743B, BD809, BD909, ++
40878	Si-P	NF/S-L, -/65V, 10A, 75W, 10MHz	17j	Rca	BD710, BD744B, BD810, BD910, ++
40879	Si-N	NF/S-L, -/85V, 10A, 75W, 7MHz	17j	Rca	BD711, BD743C, BD911
40880	Si-P	NF/S-L, -/85V, 10A, 75W, 10MHz	17j	Rca	BD712, BD744C, BD912
40881	Si-N	NF/S-L, -/40V, 10A, 75W, 7MHz	17j	Rca	BD707, BD743A, BD607, BD807, ++
40882	Si-P	NF/S-L, -/40V, 10A, 75W, 10MHz	17j	Rca	BD708, BD744A, BD808, BD908, ++
40885	Si-N	=2N6175:	15m°	Rca	→2N6175
40866	Si-N	=2N6176:	15m°	Rca	→2N6176
40867	Si-N	=2N6177:	15m°	Rca	→2N6177
40888(U)	F-Thy	=S3703SF	22a	Rca	→S3703SF
40889(U)	F-Thy	=S3702SF	22a	Rca	→S3702SF
4089	CMOS-Logic	Binary Rate Multiplier	16-DIP		—
4089	CMOS-Logic		20-MP		—
40890	Si-Di	=D2103SF	34b	Rca	→D2103SF
40891	Si-Di	=D2103S	34b	Rca	→D2103S
40892	Si-Di	=D2101S	34b	Rca	→D2101S
40893	Si-N	UHF-L, 36V, 3A, PQ>15W(470MHz)	55s	Rca	BLW15, BLX69, 2SC1336, 2SC1404
40894	Si-N	AM/FM-V, 1400MHz	5g	Rca, Sca	BF225, BF314, BF502, BF505, BF507++
40895	Si-N	AM/FM-M, 1400MHz	5g	Rca, Sca	BF225, BF314, BF502, BF505, BF507++
40896	Si-N	AM/FM-O, 1400MHz	5g	Rca, Sca	BF225, BF314, BF502, BF505, BF507++
40897	Si-N	AM/FM-ZF, 1400MHz	5g	Rca, Sca	BF225, BF314, BF502, BF505, BF507++
40898	Si-N	UHF-Tr/E, 45V, 0,35A, PQ>2W(2,3GHz)	Koax	Rca	—
40899	Si-N	UHF-Tr/E, 45V, 1,5A, PQ>6W(2,3GHz)	Koax	Rca	—
40900	Triac	=T2850A	17l	Rca	→T2850A
40901	Triac	=T2850B	17l	Rca	→T2850B
40902	Triac	=T2850D	17l	Rca	→T2850D
40909	Si-N	UHF-L, 50V, 0,7A, PQ>2W(2GHz)	Koax	Rca	—
40910	Si-N	=2N6260: 5,8W	22a°	Rca	→2N6260
40911	Si-N	=2N6261: 5,8W	22a°	Rca	→2N6261
40912	Si-N	=2N6263: 5,8W	22a°	Rca	→2N6263
40913	Si-N	=2N6264: 5,8W	22a°	Rca	→2N6264
40915	Si-N	UHF, ra, 30V, 0,04A, 2900MHz	5g	Rca, Sca	BFR15, BFS55, 2SC2498, 2SC2570
40925	Triac	=T6400N:	29l	Rca	→T6400N
40926	Triac	=T6410N:	21l	Rca	→T6410N
40927	Triac	=T6420N: Iso	54l	Rca	→T6420N
4093	CMOS-Logic	Quad 2-Input NAND Schmitt Trigger	14-DIP		—
4093	CMOS-Logic		20-MP		—
40934	Si-N	UHF-Tr/E, 36V, 0,5A, PQ>2W(470MHz)	51s	Rca	BLX68, 2SC1620
40936	Si-N	AM/SSB-L, 65V, 3,3A, PEP=20W(30MHz)	49a	Rca	—
4094	CMOS-Logic	8-Bit Shift Register with Output Latch	16-DIP		—
4094	CMOS-Logic		20-MP		—

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40940	Si-N	UHF-L, 65V, 1,5A, PQ>5W(400MHz)	55s	Rca	BLW91, 2SC2893
40941	Si-N	UHF-Tr/E, 55V, 0,4A, PQ>1W(400MHz)	51s	Rca	MRF509
40942	50Hz-Thy	=S 2400A	4a	Rca	→S 2400A
40943	50Hz-Thy	=S 2400B	4a	Rca	→S 2400B
40944	50Hz-Thy	=S 2400D	4a	Rca	→S 2400D
40945	50Hz-Thy	=S 2400M	4a	Rca	→S 2400M
4095	CMOS-Logic	Positiva Edge Triggered JK Flip-Flop	14-DIP		—
4095	CMOS-Logic	with AND Inputs, Preset and Clear	20-MP		—
40952	50Hz-Thy	=2N3873: 800V, =S 6420N	54l	Rca	→2N3873, S 6420N
40953	Si-N	VHF-Tr/E, 38V, 0,33A, PQ>2W(156MHz)	2a	Rca	BFW46, BLY33, MRF227, 2N3924
40954	Si-N	VHF-L, 38V, 4,5A, PQ>10W(156MHz)	55r	Rca	BLW38, BLY63, MRF209, 2N5591, ++
40955	Si-N	VHF-L, 36V, 5A, PQ>25W(156MHz)	55r	Rca	BLW20, BLW31, 2N6084
40956(R)	Si-Di	=D2540F(-R)	32a/b	Rca	→D2540F(-R)
40957(R)	Si-Di	=D2540A(-R)	32a/b	Rca	→D2540A(-R)
40958(R)	Si-Di	=D2540B(-R)	32a/b	Rca	→D2540B(-R)
40959(R)	Si-Di	=D2540D(-R)	32a/b	Rca	→D2540D(-R)
4096	CMOS-Logic	Positive Edge Triggered JK Flip-Flop	14-DIP		—
4096	CMOS-Logic	with AND Inputs, Preset and Clear	20-MP		—
40960(R)	Si-Di	=D2540M(-R)	32a/b	Rca	→D2540M(-R)
40964	Si-N	UHF-Tr/E, 38V, 0,2A, PQ=0,44W(470MHz)	2a	Rca, Sca	BFS50, MRF515, 2N3948
40965	Si-N	UHF-Tr/E, 38V, 0,2A, PQ=0,44W(470MHz)	2a	RcaSca	BFS50, MRF515, 2N3948
40967	Si-N	UHF-Tr/E, 38V, 0,5A, PQ>2W(470MHz)	55r	Rca	BLX67, 2N5945, 2SC2104
40968	Si-N	UHF-Tr/E, 36V, 1,5A, PQ>6W(470MHz)	55r	Rca	BLW14, BLW44, 2N5946, 2SC2105
4097	CMOS-Logic	Dual 8-Channel	24-DIP		—
4097	CMOS-Logic	Multiplexar/Demultiplexer,			—
4097	CMOS-Logic	anelog/digital			—
40970	Si-N	UHF-L, 38V, PQ>30W(470MHz)	57s	Rca	BLU45/12, MRF646, 2SC2783
40971	Si-N	UHF-L, 38V, PQ>45W(138MHz)	57s	Rca	BLV75/12, 2SC2630, 2SC3147
40972	Si-N	VHF-Tr/E, 38V, 0,33A, PQ>1,75W(175MHz)	2a	Rca	BFW48, MRF227, 2N3924
40973	Si-N	VHF-L, 38V, 4,5A, PQ>10W(175MHz)	55r	Rca	BLY89, MRF209, 2N5591, 2N6082
40974	Si-N	VHF-L, 36V, 5A, PQ>25W(175MHz)	55r	Rca	BLW20, BLW31, 2N6084
40975	Si-N	FM/VHF-O/Tr, -/30V, 0,4A	2a	Rca, Sca	BFR96, BLW16, BLY61, MRF607
40976	Si-N	FM/VHF-Tr/E, -/30V, 0,5A	2a	Rca, Sca	BFR96, BLW16, BLY61, MRF607
40977	Si-N	VHF-L, -/30V, 5A, PQ>6W(118MHz)	55r	Rca	BLW38, BLY83
40979	Si-N	=RCA1C10	17j	Rca	→RCA1C10
4098	CMOS-Logic	Dual Post-Triggerable Monoflop	16-DIP		—
4098	CMOS-Logic		20-MP		—
40980	Si-P	=RCA1C11	17j	Rca	→RCA1C11
4099	CMOS-Logic	8-Bit Addressable D-Latch	18-DIP		—
4099	CMOS-Logic		20-MP		—
40HF-10..100	Si-Di	Gl-L, 100..1000V, 40A	32a	Mot	BYX56/.., BYX97/..
40HF-10R..100R	Si-Di	=HF40	32b		—
410	Si-N	NF/S-L, 200/200V, 7A, 125W, 4MHz	23a	Rca	BUW87, BUX18(A,B), TIP180..182, ++
41002	Si-Di	=D2101S	34	Rca	→D2101S
41004	MOS-P-FET-e	NF/HF/S, 30V, Up<4V	2e	Rca	—
41008	Si-N	UHF-Tr/E, 36V, PQ>0,5W(470MHz)	51r	Rca	—
41008A	Si-N	=41008:	55r		—
41009	Si-N	UHF-Tr/E, 38V, PQ>2W(470MHz)	51r	Rca	—
41009A	Si-N	=41009:	55r		—
41010	Si-N	UHF-L, 36V, PQ>5W(470MHz)	55r	Rca	—
41012	Si-N	S-L, 120/80V, 20A, 175W, >40MHz	23a	Rca	BUV10..12, BUW57..58, BUX10..12, ++
41013	Si-N	=41012: 160/125V	23a	Rca	BUV11..12, BUW56, BUX11..12, ++
41014	Triac	=T2500B	17j	Rca	→T2500B
41015	Triac	=T2500D	17j	Rca	→T2500D
41017	F-Thy+Di	=S 3900SF	22a	Rca	→S 3800SF
41018	F-Thy+Di	=S 3800MF	22a	Rca	→S 3800MF
41019	F-Thy+Di	=S 3800E	22a	Rca	→S 3800E
4101F	Si-P	TA 4101 F (Typ-Code/Stempel/marking)	8-MDIP	Tos	→TA 4101F
41020	F-Thy+Di	=S 3800S	22a	Rca	→S 3800S
41021	F-Thy+Di	=S 3800M	22a	Rca	→S 3800M
41022	F-Thy+Di	=S 3800EF	22a	Rca	→S 3800EF
41023	F-Thy+Di	=S 3800D	22a	Rca	→S 3800D
41024	Si-N	UHF-Tr/E, 55V, 0,4A, PQ>1W(1GHz)	2a	Rca	—
41025	Si-N	UHF-L, 50V, 0,35A, PQ>3W(1GHz)	55r	Rca	—
41026	Si-N	UHF-L, 50V, 1,5A, PQ>10W(1GHz)	55r	Rca	—
41027	Si-N	UHF-L, 45V, 0,35A, PQ>3W(1GHz)	55r	Rca	—

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41028	Si-N	UHF-L, 45V, 1,5A, PQ>10W(1GHz)	55r	Rca	—
41038	Si-N	-/21V, PQ>0,75W	2a	Rca	—
41039	Si-N	VHF-A, 40V, 0,25A, >2GHz	2a	Rca, Sca	2SC1253, 2SC1366, 2SC1952
4104	CMOS-Logic	Quad Level-Changer, non	16-DIP		—
4104	CMOS-Logic	inverting/inverting			—
41042	Si-N	FM/VHF-L, 65V, 90W(Tc=75°)	55r	Rca	—
41044	Si-N	HF-Tr/E, 40V, 5W(Tc=100°)	62b	Rca	—
411	Si-N	=410: 300/300V	23a	Rca	BUX 18A, B, TIP 160..162, 2SC2961, ++
413	Si-N	=410: 400/325V	23a	Rca	BUX 18B, TIP 162, 2SC2625, 2SC2961, ++
41420	F-Thy+Di	≈BStCC0146R	22a	Rca	→BStCC0146R
41500	Si-N	NF/S-L, 35V, 7A, 40W, >4MHz	17j	Rca	BD243, BD543, BD795, BD805, ++
41501	Si-P	NF/S-L, 35V, 7A, 40W, >4MHz	17j	Rca	BD 244, BD544, BD796, BD806, ++
41502	Si-N	Uni, -/30V, 1A, 0,8W	2a	Rca, Sca	BC140..141, BCX40, 2N1990, 2N2102, ++
41503	Si-P	Uni, -/30V, 1A, 0,8W	2a	RcaSca	BC160..161, BCX60, 2SA606
41504	Si-N	NF/S-L, 35V, 4A, 36W, >0,8MHz	17j	Rca	BD 243, BD533, BD539, BD947, ++
41505	Si-N	NF/S-L, -/200V, 1A, 20W, 20MHz	15m	Rca	(BD410, BUV63)
41506	Si-N	S-L, 200/200V, 3A, 100W	23a	Rca, Sca	2SD632
41508	Si-N	S-L, -/140V, 30A(ss), 150W	23a	Rca	BD249F, BUW58, BUW73, 2SC2865(A), ++
42	Si-Di	=BAT 54AW (Typ-Code/Stempel/marking)	35(2mm)		→BAT 54AW
423	Si-N	=410: 400/325V	23a	Rca	BUX 18B, TIP 162, 2SC2625, 2SC2961, ++
43	Si-Di	=BAT 54CW (Typ-Code/Stempel/marking)	35(2mm)		→BAT 54CW
43(s)	Si-Di	=BAS 40 (Typ-Code/Stempel/marking)	35		→BAS 40
431	Si-N	=410: 400/325V	23a	Rca	BUX 18B, TIP 162, 2SC2625, 2SC2961, ++
43104	Si-N	S-L, 160/140V, 16A, 150W, >0,2MHz	23a	Spc	BD745F, BUW58, BUW73, 2SC2865(A), ++
43879(R)	Si-Di	=D2406F(-R)	32a/b	Rca	→D2406F(-R)
43880(R)	Si-Di	=D2406A(-R)	32a/b	Rca	→D2406A(-R)
43661(R)	Si-Di	=D2406B(-R)	32a/b	Rca	→D2406B(-R)
43862(R)	Si-Di	=D2406C(-R)	32a/b	Rca	→D2406C(-R)
43883(R)	Si-Di	=D2406D(-R)	32a/b	Rca	→D2406D(-R)
43864(R)	Si-Di	=D2406M(-R)	32a/b	Rca	→D2406M(-R)
43889(R)	Si-Di	=D2412F(-R)	32a/b	Rca	→D2412F(-R)
43890(R)	Si-Di	=D2412A(-R)	32a/b	Rca	→D2412A(-R)
43891(R)	Si-Di	=D2412B(-R)	32a/b	Rca	→D2412B(-R)
43892(R)	Si-Di	=D2412C(-R)	32a/b	Rca	→D2412C(-R)
43893(R)	Si-Di	=D2412D(-R)	32a/b	Rca	→D2412D(-R)
43894(R)	Si-Di	=D2412M(-R)	32a/b	Rca	→D2412M(-R)
43899(R)	Si-Di	=D2520F(-R)	32a/b	Rca	→D2520F(-R)
43900(R)	Si-Di	=D2520A(-R)	32a/b	Rca	→D2520A(-R)
43901(R)	Si-Di	=D2520B(-R)	32a/b	Rca	→D2520B(-R)
43902(R)	Si-Di	=D2520C(-R)	32a/b	Rca	→D2520C(-R)
43903(R)	Si-Di	=D2520D(-R)	32a/b	Rca	→D2520D(-R)
43904(R)	Si-Di	=D2520M(-R)	32a/b	Rca	→D2520M(-R)
43Y	Z-Di	=BZV 49/C43 (Typ-Code/Stempel/marking)	39		→BZV 49/C43
44	Si-Di	=BAT 54SW (Typ-Code/Stempel/marking)	35(2mm)		→BAT 54SW
44(s)	Si-Di	=BAS 40-04 (Typ-Code/Stempel/marking)	35		→BAS 40-04
44001	Si-Di	=1N4001	31e	Rca	→1N4001
44002	Si-Di	=1N4002	31e	Rca	→1N4002
44003	Si-Di	=1N4003	31a	Rca	→1N4003
44004	Si-Di	=1N4004	31a	Rca	→1N4004
44005	Si-Di	=1N4005	31a	Rca	→1N4005
44006	Si-Di	=1N4006	31a	Rca	→1N4006
44007	Si-Di	=1N4007	31a	Rca	→1N4007
4402	CMOS-Logic	Dual 4-Input NOR Gate with Transistor	16-DIP		—
4402	CMOS-Logic	output1			—
4412	CMOS-Logic	Dual 4-Input NAND Gate with	16-DIP		—
4412	CMOS-Logic	Transistor output			—
4415	CMOS-Logic	Quad Precision Timer/Driver	16-DIP		—
4426	CMOS-Logic	Decimal Up Counter with	16-DIP		—
4426	CMOS-Logic	7-Segment-Decoder			—
4428	CMOS-Logic	BCD-to-Decimal Decoder	14-DIP		—
4433	CMOS-Logic	Decimal Up Counter with	16-DIP		—
4433	CMOS-Logic	7-Segment-Decoder and ripple blanking			—
4441	CMOS-Logic	Quad True/Complement Buffer	14-DIP		—
4449	CMOS-Logic	Hex True/Complement Buffer	16-DIP		—
4490	CMOS-Logic	Hex Contac1 Bounca Eliminator	16-DIP		—
44933	Si-Di	=D2201F	31a	Rca	→D2201F

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44934	Si-Di	=D2201A	31a	Rca	→D2201A
44935	Si-Di	=D2201B	31a	Rca	→D2201B
44936	Si-Di	=D2201D	31a	Rca	→D2201D
44937	Si-Di	=D2201M	31a	Rca	→D2201M
44936	Si-Di	=D2201N	31a	Rca	→D2201N
45(s)	Si-Di	=BAS 40-05 (Typ-Code/Stempel/marking)	35		→BAS 40-05
4500	CMOS-Logic	1-Bit Processing Unit	16-DIP		—
4501	CMOS-Logic	Dual 4-Input NAND Gate, 2-Input	16-DIP		—
4501	CMOS-Logic	NOR/OR Gate			—
4502	CMOS-Logic	Hex Inverter/Buffer	16-DIP		—
4502	CMOS-Logic		20-MP		—
4503	CMOS-Logic	Hex Buffer/Driver, non inverting	16-DIP		—
4503	CMOS-Logic		20-MP		—
4504	CMOS-Logic	Hex Level Shifter (TTL/CMOS or	16-DIP		—
4504	CMOS-Logic	CMOS/CMOS)			—
4505	CMOS-Logic	64x1-Bit RAM	14-DIP		—
4506	CMOS-Logic	Dual AND/OR/Inverter	16-DIP		—
4506	CMOS-Logic	Combination-Gate, expandable			—
4507	CMOS-Logic	Quad 2-Input EX-OR Gate	14-DIP		—
4506	CMOS-Logic	Dual 4-Bit RS Flip-Flop	24-DIP		—
4510	CMOS-Logic	Synchronous Decimal Up/Down Counter	16-DIP		—
4510	CMOS-Logic	with Preset	20-MP		—
4511	CMOS-Logic	BCD-to-7-Segment Decoder/Memory/Driver	16-DIP		—
4511	CMOS-Logic		20-MP		—
4512	CMOS-Logic	8-to-1 Data Selector/Multiplexer with	16-DIP		—
4512	CMOS-Logic	Enable	20-MP		—
4513	CMOS-Logic	BCD-to-7-Segment	18-DIP		—
4513	CMOS-Logic	Decoder/Memory/Display Driver with			—
4513		Ripple Blanking			—
4514	CMOS-Logic	4-Bit Binary Decoder/Demultiplexer	24-DIP		—
4514	CMOS-Logic	with Input Latch			—
4515	CMOS-Logic	4-Bit Binary Decoder/Demultiplexer	24-DIP		—
4515	CMOS-Logic	with Input Latch			—
4516	CMOS-Logic	Synchronous Binary 4-Bit Up/Down	16-DIP		—
4516	CMOS-Logic	Counter with Preset	20-MP		—
4517	CMOS-Logic	Dual 64-Bit Serial Shift Register	16-DIP		—
4517	CMOS-Logic		20-MP		—
4518	CMOS-Logic	Dual Synchronous Decimal Up Counter	16-DIP		—
4516	CMOS-Logic		20-MP		—
4519	CMOS-Logic	Quad Common Addressable 2-to-1	16-DIP		—
4519	CMOS-Logic	Multiplexer			—
45190	Si-N	NF/S-L, -/40V, 7A, 40W, >2MHz	17h	Rca	(BD243A, BD543A, BD797, BD607,++)
45191	Si-N	=45190: -/60V	17h	Rca	(BD243B, BD543B, BD799, BD809,++)
45192	Si-N	=45190: -/90V	17h	Rca	(BD243C, BD543C, BD801, BD711,++)
45193	Si-P	NF/S-L, -/40V, 7A, 40W, >2MHz	17h	Rca	(BD244A, BD544A, BD798, BD808,++)
45194	Si-P	=45193:-/60V	17h	Rca	(BD244B, BD544B, BD800, BD810,++)
45195	Si-P	=45193:-/80V	17h	Rca	(BD244C, BD544C, BD802, BD712,++)
4520	CMOS-Logic	Dual Synchronous Binary Up Counter	16-DIP		—
4520	CMOS-Logic		20-MP		—
4521	CMOS-Logic	24-Bit Binary Divider/Counter	16-DIP		—
4521	CMOS-Logic		20-MP		—
4522	CMOS-Logic	4-Bit BCD Down Counter with Preset	16-DIP		—
4522	CMOS-Logic		20-MP		—
4524	CMOS-Logic	256x4-Bit Read Only Memory (ROM)	16-DIP		—
4526	CMOS-Logic	4-Bit Binary Down Counter with Preset	16-DIP		—
4527	CMOS-Logic	Decimal Rate Multiplier	16-DIP		—
4527	CMOS-Logic		20-MP		—
4526	CMOS-Logic	Dual Post-Triggerable Monoflop with	16-DIP		—
4528	CMOS-Logic	Clear			—
4529	CMOS-Logic	Dual 4-Channel Analog Multiplexer	16-DIP		—
4529	CMOS-Logic		20-MP		—
4530	CMOS-Logic	Dual 5-Input Majority Logic Gate	16-DIP		—
4531	CMOS-Logic	12-Bit Parity Unit	16-DIP		—
4532	CMOS-Logic	3-Bit Priority Coder	16-DIP		—
4532	CMOS-Logic		20-MP		—
4534	CMOS-Logic	Pental Count Decades with	24-DIP		—

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4534	CMOS-Logic	Multiplex-Outputs			—
4536	CMOS-Logic	Programmable Timer	16-DIP		—
4536	CMOS-Logic		20-MP		—
4537	CMOS-Logic	256x1-Bit RAM	16-DIP		—
4538	CMOS-Logic	Dual Post-Triggerable Pecision	16-DIP		—
4538	CMOS-Logic	Monoflop	20-MP		—
4539	CMOS-Logic	Dual 4-to-1 Data Selector/Multiplexer	16-DIP		—
4541	CMOS-Logic	Programmable Timerwith RC-Oscillator	14-DIP		—
4541	CMOS-Logic		20-MP		—
45411	Diac	=D3202Y		Rca	→D3202Y
45412	Diac	=D3202U		Rca	→D3202U
4543	CMOS-Logic	BCD-to-7-Segment Decoder/Memory/Driver	16-DIP		—
4543	CMOS-Logic		20-MP		—
4544	CMOS-Logic	BCD-to-7-Segment	18-DIP		—
4544	CMOS-Logic	Decoder/Memory/Display Dnverwith			—
4544		Ripple Blanking			—
4547	CMOS-Logic	BCD-to-7-Segment Decoder/Power Driver	16-DIP		—
4548	CMOS-Logic	Dual Post-Triggerable Monoflop	16-DIP		—
4549	CMOS-Logic	8-Bit Register for Successive	16-DIP		—
4549	CMOS-Logic	Approximation in A/D-Changer			—
4551	CMOS-Logic	Quad 2-Channel Analog Multiplexer	16-DIP		—
4552	CMOS-Logic	64x4-Bit RAM	24-DIP		—
4553	CMOS-Logic	3-Placa Dacimal Up Counter	16-DIP		—
4554	CMOS-Logic	Dual 2-Bit Parallel Binary Multiplier	16-DIP		—
4555	CMOS-Logic	Dual 2-Bit Damultiplexer	16-DIP		—
4555	CMOS-Logic		20-MP		—
4556	CMOS-Logic	Dual 2-Bit Demultiplexer	16-DIP		—
4556	CMOS-Logic		20-MP		—
4557	CMOS-Logic	64-Bit Serial Shift Register,	16-DIP		—
4557	CMOS-Logic	presetable 1-64 Bit			—
4558	CMOS-Logic	BCD-to-7-Segment Decoder	16-DIP		—
4559	CMOS-Logic	8-Bit Register for Successive	16-DIP		—
4559	CMOS-Logic	Approximation in A/D-Changer			—
4560	CMOS-Logic	4-Bit BCD Adder	16-DIP		—
4561	CMOS-Logic	9-s Complementer	14-DIP		—
4562	CMOS-Logic	128-Bit Shift Register with parallel	16 DIP		—
4562	CMOS-Logic	Outputs			—
4566	CMOS-Logic	Universal Timebase Generator	16-DIP		—
4566	CMOS-Logic		20-MP		—
4568	CMOS-Logic	Phase Comparator and Counterwith	16-DIP		—
4568	CMOS-Logic	Preset			—
4569	CMOS-Logic	Dual Fast 4-Bit Down Counterwith	16-DIP		—
4569	CMOS-Logic	Preset			—
4572	CMOS-Logic	Quad Inverters, 1 NOR Gate and NAND	16-DIP		—
4572	CMOS-Logic	Gate			—
4573	CMOS-Logic	Quad Programmable Op Amp	16-DIP		—
4574	CMOS-Logic	Quad Programmable Comparetor	16-DIP		—
4575	CMOS-Logic	Dual Programmable Op Amp and	16-DIP		—
4575	CMOS-Logic	Comparetor			—
4578	CMOS-Logic	Comparetor with Voltage Follower	16-DIP		—
4580	CMOS-Logic	4x4-Bit Multiport Register	24-DIP		—
4581	CMOS-Logic	4-Bit Arithmetic/Logic Unit (ALU)	24-DIP		—
4562	CMOS-Logic	Carry Generator	16-DIP		—
4563	CMOS-Logic	Dual Schmitt Trigger with presetable	16-DIP		—
4563	CMOS-Logic	Hysterese			—
4564	CMOS-Logic	Hex Schmitt Trigger Inverter	14-DIP		—
4565	CMOS-Logic	4-Bit Comparator	16-DIP		—
4565	CMOS-Logic		20-MP		—
4597	CMOS-Logic	8-Bit D-Latch with Counter, non	16-DIP		—
4597	CMOS-Logic	Inverting, Bus Compatible			—
4598	CMOS-Logic	8-Bit Bus Compatible Addressable	18-DIP		—
4598	CMOS-Logic	D-Latch			—
4599	CMOS-Logic	8-Bit Addressable D-Latch	18-DIP		—
46(s)	Si-Di	=BAS 40-06 (Typ-Code/Stempel/marking)	35		→BAS 40-06
47(s)	Si-Di	=BAS 40-07 (Typ-Code/Stempel/marking)	44		→BAS 40-07
4720	CMOS-Logic	256x1-Bit RAM	16-DIP		—

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4723	CMOS-Logic	Dual 4-Bit Addressable Latch with	16-DIP		—
4723	CMOS-Logic	Clear, non inverting			—
4724	CMOS-Logic	8-Bit Addressable D-Latch	16-DIP		—
4724	CMOS-Logic		20-MP		—
4731	CMOS-Logic	Quad 64-Bit Serial Shift Register	14-DIP		—
4737	CMOS-Logic	4 1/2 Decade Counter	18-DIP		—
47Y	Z-Di	=BZV49/C47 (Typ-Code/Stempel/marking)	39		→BZV49/C47
4A	Si-P	=BC 859AW (Typ-Code/Stempel/marking)	35(2mm)		→BC 859W
4A	C-Di	=MA72 (Typ-Code/Stempel/marking)	71(2,7mm)		→MA72
4A	C-Di	=MMBV 109 (Typ-Code/Stempel/marking)	35		→MMBV 109
4A(p,s)	Si-P	=BC 859A (Typ-Code/Stempel/marking)	35		→BC 859
4AA11	Si-P	4xPNP, -/60V, 3A, 2W, B>60	8-SIP	Rhm	—
4AA12	Si-P-Darl+Di	4x Darl, -/120V, 6A, 2W, B>2000	8-SIP	Rhm	—
4AC12	Si-N-Darl+Di	4x Darl, Z-Di, 27V, 2A, 28W, B>7000	10-SIP	Hit	—
4AC13	Si-N-Darl+Di	4x Darl, Z-Di, 50V, 5A, 28W, B>2000	10-SIP	Hit	—
4AC14	Si-N-Darl+Di	4x Darl, Z-Di, 150V, 5A, 28W, B>1000	10-SIP	Hit	—
4AC15	Si-N	4xNPN, -/60V, 3A, 2W, B>60	10-SIP	Rhm	—
4AC18	Si-N-Darl+Di	4x Darl, Z-Di, -/60V, 2A, 2W, B>2000	10-SIP	Rhm	—
4AC17	Si-N-Darl+Di	4x Darl, Z-Di, -/60V, 4A, 2W, B>2000	10-SIP	Rhm	—
4AC18	Si-N-Darl+Di	4x Darl, -/100V, 3A, 2W, B>2000	10-SIP	Rhm	—
4AC19	Si-N-Darl+Di	4x Darl, -/200V, 2,5A, 2W, B>1000	10-SIP	Rhm	—
4AC20	Si-N-Darl+Di	4x Darl, -/100V, 2A, 2W, B>2000	10-SIP	Rhm	—
4AC21	Si-N-Darl+Di	4x Darl, Z-Di, -/72V, 2A, 2W, B>2000	10-SIP	Rhm	—
4AC22	Si-N-Darl+Di	4x Darl, Z-Di, -/100V, 2A, 2W, B>1000	10-SIP	Rhm	—
4AC23	Si-N-Darl	4x Darl, Z-Di, -/100V, 3A, 2W, B>1000	10-SIP	Rhm	—
4AC24	Si-N	4x NPN, hi-beta, -/80V, 3A, 2W, B>600	10-SIP	Rhm	—
4AC25	Si-N-Darl+Di	4x Darl, Z-Di, -/60V, 2A, 2W, B>2000	10-SIP	Rhm	—
4AC26	Si-N-Darl+Di	4x Darl, Z-Di, -/100V, 2A, 2W, B>1000	10-SIP	Rhm	—
4AE11	Si-N/P-Darl	2xN- +2xP-Darl, 300/300V, 0,3A, 32W	12-SIL	Hit	—
4AE12	Si-N/P	2x NPN+2x PNP, -/50V, 3A, 2W, B>60	10-SIP	Rhm	—
4AJ11	MOS-P-FET-e*	=4x2SJ173: 8A, 28W	12-SIP	Hit	—
4AK15	MOS-N-FET-e*	=4x2SK971: 8A, 28W	10-SIP	Hit	—
4AK18	MOS-N-FET-e	=4x2SK974: 5A, 28W	10-SIP	Hit	—
4AK17	MOS-N-FET-e*	=4x2SK972: 10A, 28W	10-SIP	Hit	—
4AK18	MOS-N-FET-e	=4x2SK973: 2,5A, 28W	10-SIP	Hit	—
4AK19	MOS-N-FET-e*	4x V-MOS, LogL, 120V, 5A, 28W, <0,5Ω	10-SIP	Hit	—
4AK20	MOS-N-FET-e*	=4x2SK1300: 5A, 28W	10-SIP	Hit	—
4AK21	MOS-N-FET-e	=4x2SK1302: 8A, 28W	10-SIP	Hit	—
4AK22	MOS-N-FET-e*	=4x2SK1254: 3A, 28W	10-SIP	Hit	—
4AK23	MOS-N-FET-e*	=4x2SK1300: 5A, 32W	10-SIL	Hit	—
4AK25	MOS-N-FET-e	=4x2SK975: 1,5A, 24W	10-SIP	Hit	—
4AK26	MOS-N-FET-e*	=4x2SK972: 10A, 28W	12-SIP	Hit	—
4AK27	MOS-N-FET-e*	=4x2SK1949: 5A, 28W	10-SIP	Hit	—
4AM11	MOS-P/N-FET*	=2x2SJ172+2x2SK970: 5A, 28W	10-SIP	Hit	—
4AM12	MOS-P/N-FET*	=2x2SJ173+2x2SK971: 8A, 28W	10-SIP	Hit	—
4AM13	MOS-P/N-FET*	=2x2SJ182+2x2SK973: 3A, 28W	10-SIP	Hit	—
4AM14	MOS-P/N-FET*	=2x2SJ172+2x2SK970: 8A, 32W	12-SIL	Hit	—
4AM15	MOS-P/N-FET	=2x2SJ114+2x2SK400: 4A, 32W	12-SIL	Hit	—
4AM16	MOS-P/N-FET*	=2x2SJ172+2x2SK970: 8A, 28W	12-SIP	Hit	—
4AM17	MOS-P/N-FET*	=2x2SJ236+2x2SK1776: 8A, 28W	12-SIP	Hit	—
4AR	Si-P	=BC 859AR (Typ-Code/Stempel/marking)	35		→BC859AR
4As	Si-P	=BC 859AW (Typ-Code/Stempel/marking)	35(2mm)		→BC 859W
4B	Si-N	=2SC4238 (Typ-Code/Stempel/marking)	35		→2SC4238
4B	Si-N	=2SC4670 (Typ-Code/Stempel/marking)	35(2mm)		→2SC4670
4B	Si-P	=BC 859BW (Typ-Code/Stempel/marking)	35(2mm)		→BC 859W
4B	C-Di	=MA73 (Typ-Code/Stempel/marking)	71(2,7mm)		→MA73
4B	C-Di	=MA77 (Typ-Code/Stempel/marking)	71(1,7mm)		→MA77
4B	C-Di	=MMBV 432 (Typ-Code/Stempel/marking)	35		→MMBV 432
4B(p,s)	Si-P	=BC 859B (Typ-Code/Stempel/marking)	35		→BC 859
4BR	Si-P	=BC 859BR (Typ-Code/Stempel/marking)	35		→BC 859BR
4Bs	Si-P	=BC 859BW (Typ-Code/Stempel/marking)	35(2mm)		→BC 859W
4C	Si-N	=2SC4239 (Typ-Code/Stempel/marking)	35(2mm)		→2SC4239
4C	MOS-N-FET-d	=3SK200 (Typ-Code/Stempel/marking)	44		→3SK200
4C	MOS-N-FET-d	=3SK269 (Typ-Code/Stempel/marking)	44(2mm)		→2SK269
4C	Si-P	=BC 859CW (Typ-Code/Stempel/marking)	35(2mm)		→BC859W
4C	C-Di	=FMMD3102 (Typ-Code/Stempel/marking)	35		→FMMD3102

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4C	C-Di	=MA79 (Typ-Code/Stempel/marking)	71(1,7mm)		→MA79
4C	C-Di	=MMBV 3102 (Typ-Code/Stempel/marking)	35		→MMBV3102
4C(p,s)	Si-P	=BC 859C (Typ-Code/Stempel/marking)	35		→BC859
4CR	Si-P	=BC 859CR (Typ-Code/Stempel/marking)	35		→BC859CR
4Cs	Si-P	=BC 859CW (Typ-Code/Stempel/marking)	35(2mm)		→BC859W
4D	P-FET	=2SJ148 (Typ-Code/Stempel/marking)	35		→2SJ146
4D	Si-P	=BC 859W (Typ-Code/Stempel/marking)	35(2mm)		→BC859W
4D	Si-Di	=HD3A (Typ-Code/Stempel/marking)	35		→HD3A
4D	Si-Di	=HD3A (Typ-Code/Stempel/marking)	35		→HD3A
4D	C-Di	=MA81 (Typ-Code/Stempel/marking)	71(1,7mm)		→MA81
4D	C-Di	=MMBV 3401 (Typ-Code/Stempel/marking)	35		→MMBV3401
4D	C-Di	=MMSV 3401 (Typ-Code/Stempel/marking)	71a(2,7mm)		→MMSV3401
4D(p)	Si-P	=BC 859 (Typ-Code/Stempel/marking)	35		→BC859
4E	Si-P	=BC 860AW (Typ-Code/Stempel/marking)	35(2mm)		→BC860W
4E	Si-P	=FMMT-A92 (Typ-Code/Stempel/marking)	35		→FMMT-A92
4E	C-Di	=MMBV 105G (Typ-Code/Stempel/marking)	35		→MMBV105G
4E(p,s)	Si-P	=BC 860A (Typ-Code/Stempel/marking)	35		→BC860
4E100-8	Trigger-Di	=4E20-8: Ub=90..110V	31a		4E100M
4E100A	Trigger-Di	=4E20A: Ub=80..120V	31a		4E100M
4E100M-8	Trigger-Di	=4E20M-8: Ub=60..115V	31a		4E100A
4E20-8	Trigger-Di	Ub=16..24V, Is<125µA, Itsm=5A	31a	Itt	4E20M
4E200-8	Trigger-Di	=4E20-8: Ub=160..220V	31a		4E200M
4E200A	Trigger-Di	=4E20A: Ub=170..230V	31a		4E200M
4E200M-8	Trigger-Di	=4E20M-8: Ub=180..230V	31a		4E200A
4E20A	Trigger-Di	Ub=14..26V, Itsm=5A	31a	Itt	4E20M
4E20M-8	Trigger-Di	Ub=14..25V, Itsm=5A	31a	Itt	4E20A
4E30-8	Trigger-Di	=4E20-8: Ub=26..34V	31a		4E30M
4E30A	Trigger-Di	=4E20A: Ub=24..36V	31a		4E30M
4E30M-8	Trigger-Di	=4E20M-8: Ub=23..36V	31a		4E30A
4E40-8	Trigger-Di	=4E20-8: Ub=36..44V	31a		4E40M
4E40A	Trigger-Di	=4E20A: Ub=34..48V	31a		4E40M
4E40M-8	Trigger-Di	=4E20M-8: Ub=32..48V	31a		4E40A
4E50-8	Trigger-Di	=4E20-8: Ub=48..54V	31a		4E50M
4E50A	Trigger-Di	=4E20A: Ub=44..56V	31a		4E50M
4E50M-8	Trigger-Di	=4E20M-8: Ub=41..57V	31a		4E50A
4ER	Si-P	=BC 860AR (Typ-Code/Stempel/marking)	35		→BC860R
4EX580	Trigger-Di	Ub=15..25V, Is<0,25mA, Itsm=5A	31a	Itt	4E20M
4EX581	Trigger-Di	=4EX560: Ub=25..35V	31a		4E30M
4EX582	Trigger-Di	=4EX560: Ub=35..50V	31a		4E40M
4F	Si-N	=2SC4444 (Typ-Code/Stempel/marking)	35		→2SC4444
4F	Si-N	=2SC4971 (Typ-Code/Stempel/marking)	35		→2SC4971
4F	Si-P	=BC 860BW (Typ-Code/Stempel/marking)	35(2mm)		→BC860W
4F(p,s)	Si-P	=BC 860B (Typ-Code/Stempel/marking)	35		→BC850
4FR	Si-P	=BC 860BR (Typ-Code/Stempel/marking)	35		→BC860R
4Fs	Si-P	=BC 860BW (Typ-Code/Stempel/marking)	35(2mm)		→BC860W
4G	Si-P	=BC 860CW (Typ-Code/Stempel/marking)	35(2mm)		→BC860W
4G	Si-N	=FMMT 2484 (Typ-Code/Stempel/marking)	35		→FMMT2484
4G	C-Di	=MMBV 2101 (Typ-Code/Stempel/marking)	35		→MMBV2101
4G(p,s)	Si-P	=BC 860C (Typ-Code/Stempel/marking)	35		→BC860
4GR	Si-P	=BC 860CR (Typ-Code/Stempel/marking)	35		→BC860CR
4Gs	Si-P	=BC 860CW (Typ-Code/Stempel/marking)	35(2mm)		→BC860W
4GZ..R	Z-Di	=4GZ..:	32b	Ssc	BZX98/..R, BZY93/..R
4GZ10A..82A	Z-Di	10..82V, 10%, 4W(Tc=75°)	32a	Ssc	BZX98/.., BZY93/..
4GZ10B..18B	Z-Di	100..160V, 10%, 4W(Tc=75°)	32a	Ssc	BZX98/..
4H	Si-P	=BC 860W (Typ-Code/Stempel/marking)	35(2mm)		→BC860W
4H	C-Di	=MMBV 2103 (Typ-Code/Stempel/marking)	35		→MMBV2103
4H(p)	Si-P	=BC 860 (Typ-Code/Stempel/marking)	35		→BC860
4J	C-Di	=MMBV 2109 (Typ-Code/Stempel/marking)	35		→MMBV2109
4J100-5	Trigger-Di	=4J50-5: Ub=90..110V	34a		4E100M
4J200-5	Trigger-Di	=4J50-5: Ub=160..220V	34a		4E200M
4J50-5	Trigger-Di	Ub=45..55V, Is<0,25mA	34a	Itt	4E50M
4K	C-Di	=MMBV 2097 (Typ-Code/Stempel/marking)	35		→MMBV2097
4L	C-Di	=MMBV 2098 (Typ-Code/Stempel/marking)	35		→MMBV2098
4LO	N-FET	=2SK1103-O (Typ-Code/Stempel/marking)	35		→2SK1103
4LP	N-FET	=2SK1103-P (Typ-Code/Stempel/marking)	35		→2SK1103
4LQ	N-FET	=2SK1103-Q (Typ-Code/Stempel/marking)	35		→2SK1103

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4LR	N-FET	=2SK1103-R (Typ-Code/Stempel/marking)	35		→2SK1103
4M	Si-Di	=MMBD 101 (Typ-Code/Stempel/marking)	35		→MMBD101
4MO	P-FET	=2SJ163-O (Typ-Code/Stempel/marking)	35		→2SJ163
4MP	P-FET	=2SJ163-P (Typ-Code/Stempel/marking)	35		→2SJ163
4MQ	P-FET	=2SJ163-Q (Typ-Code/Stempel/marking)	35		→2SJ163
4MR	P-FET	=2SJ163-R (Typ-Code/Stempel/marking)	35		→2SJ163
4N	Si-P/N	=XN 5601 (Typ-Code/Stempel/marking)	46		→XN 5601
4N	Si-P/N	=XP 5601 (Typ-Code/Stempel/marking)	46(2mm)		→XP 5601
4N	Opto	Optokoppler/opto coupled isolator			—
4O	Si-P	=2SA1721-O (Typ-Code/Stempel/marking)	35		→2SA1721
4O	Si-N	=XN 1507 (Typ-Code/Stempel/marking)	45		→XN 1507
4O	Si-N	=XP 1507 (Typ-Code/Stempel/marking)	45(2mm)		→XP 1507
4P	Si-N/P	=XN 1A312 (Typ-Code/Stempel/marking)	45		→XN 1A312
4Q	Si-P/N	=XN 1B301 (Typ-Code/Stempel/marking)	45		→XN 1B301
4Q	Si-P/N	=XP 1B301 (Typ-Code/Stempel/marking)	45(2mm)		→XP 1B301
4R	Si-P	=2SA1721-R (Typ-Code/Stempel/marking)	35		→2SA1721
4R	C-Di	=MMBV 3700 (Typ-Code/Stempel/marking)	35		→MMBV 3700
4R	Si-P/N	=XN 1C301 (Typ-Code/Stempel/marking)	45		→XN 1C301
4R	Si-P/N	=XP 1C301 (Typ-Code/Stempel/marking)	45(2mm)		→XP 1C301
4S	Si-Di	=MMBD 201 (Typ-Code/Stempel/marking)	35		→MMBD201
4S	Si-P+R	=XN 611FH (Typ-Code/Stempel/marking)	46		→XN611FH
4S	Si-P+R	=XP 611FH (Typ-Code/Stempel/marking)	46(2mm)		→XP611FH
4T	N-FET	=2SK1216 (Typ-Code/Stempel/marking)	35		→2SK1216
4T	Si-Di	=MMBD 301 (Typ-Code/Stempel/marking)	35		→MMBD301
4U	C-Di	=MMBV 2105 (Typ-Code/Stempel/marking)	35		→MMBV 2105
4U	Si-N	=XN 5553 (Typ Code/Stempel/marking)	46		→XN5553
4U	Si-N	=XP 5553 (Typ-Code/Stempel/marking)	46(2mm)		→XP 5553
4V	MOS-N-FET-e	=2SK1226 (Typ-Code/Stempel/marking)	35		→2SK1228
4V	MOS-N-FET-e	≈2SK1374 (Typ Code/Stempel/marking)	35(2mm)		→2SK1374
4V	C-Di	=MMBV 2106 (Typ-Code/Stempel/marking)	35		→MMBV2106
4W	C-Di	=MMBV 2107 (Typ-Code/Stempel/marking)	35		→MMBV2107
4X	Si-N	=2SC4515 (Typ-Code/Stempel/marking)	44		→2SC4515
4X	C-Di	=MMBV 2108 (Typ-Code/Stempel/marking)	35		→MMBV2106
4Y	Si-N	=2SC4516 (Typ-Code/Stempel/marking)	44		→2SC4516
4Y	C-Di	=MMBV 2102 (Typ-Code/Stempel/marking)	35		→MMBV2102
4Y3	Z-Di	=BZV 49/C4V3(Typ-Code/Stempel/marking)	39		→BZV 49/C4V3
4Y7	Z-Di	BZV 49/C4V7(Typ-Code/tempel/marking)	39		→BZV 49/C4V7
4Z	C-Di	=MMBV 2104 (Typ-Code/Stempel/marking)	35		→MMBV 2104
5		**5**			
5	C-Di	=1SV202 (Typ-Code/Stempel/marking)	71 (2,7mm)		→1SV202
5	C-Di	=HVR 300 (Typ-Code/Stempel/marking)	71 (2,7mm)		→HVR300
5	C-Di	=HVU202 (Typ-Code/Stempel/marking)	71 (1,7mm)		→HVU202
5.1B	Z-Di	=HZF 5.1 BP (Typ-Code/Stempel/marking)	71 (5mm)		→HZF 5.1BP
5.1C	Z-Di	=HZF 5.1 CP (Typ-Code/Stempel/marking)	71 (5mm)		→HZF 5.1CP
5.6B	Z-Di	=HZF 5.6BP (Typ-Code/Stempel/marking)	71 (5mm)		→HZF 5.6BP
5.6C	Z-Di	=HZF 5.6CP (Typ-Code/Stempel/marking)	71 (5mm)		→HZF 5.6CP
504 BSY	N-FET	=BSV 78	2b	Phi	→BSV 78
508 BSY	MOS-N-FET-d	=BSV 81	5m	Phi	→BSV 81
51Y	Z-Di	=BZV 49/C51 (Typ-Code/Stempel/marking)	39		→BZV49/C51
52530A	Si-N	≈BU 326A	23a		→BU 326A
528BSY	MOS-N-FET-e	≈2N4351	5m	Phi	→2N4351
53	Si-Di	=BAT 17 (Typ-Code/Stempel/marking)	35		→BAT 17
54	Si-Di	=BAT 17-04 (Typ-Code/Stempel/marking)	35		→BAT 17-04
55	Si-Di	=BAT 17-05 (Typ-Code/Stempel/marking)	35		→BAT 17-05
555 BRY	PUT	=BRY 61	35b	Phi	→BRY 61
556 BCYA	Si-P	=BCX 17	35a	Phi	→BCX 17
556 BCYB	Si-P	=BCX 18	35a	Phi	→BCX 18
557 BCYA	Si-N	=BCX 19	35a	Phi	→BCX 19
557 BCYB	Si-N	=BCX 20	35a	Phi	→BCX 20
56	Si-Di	=BAT 17-06 (Typ-Code/Stempel/marking)	35		→BAT 17-06
5609	Si-N	→CS 5609			—
5610	Si-P	→CS 5610			—
563 BSY	Si-P	=BSS 63	35a	Phi	→BSS 63
564 BSY	Si-N	=BSS 64	35a	Phi	→BSS 64
565 BAT	Si-Di	=BAT 17	35p	Phi	→BAT 17

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56Y	Z-Di	=BZV 49/C56 (Typ-Code/Stempel/marking)	39		→BZV 49/C56
57	Si-Di	=BAT 17-07 (Typ-Code/Stempel/marking)	44		→BAT 17-07
57	Si-N	=BFQ 57 (Typ-Code/Stempel/marking)	52		→BFQ57
574 BAT	Si-Di	=BAT 18	35p	Phi	→BAT 18
58	Si-N	=BFQ 56 (Typ-Code/Stempel/marking)	52		→BFQ 58
59	Si-N	=BFQ 59 (Typ-Code/Stempel/marking)	51		→BFQ 59
5P	Si-P	=BC 807-16W (Typ-Code/Stempel/marking)	35(2mm)		→BC 807W
5P	Si-Di	=FMMD 6050 (Typ-Code/Stempel/marking)	35		→FMMD 6050
5P	Si-Di	=MMBD 6050 (Typ-Code/Stempel/marking)	35		→MMBD 6050
5P	Si-Di	=PMBD 6050 (Typ-Code/Stempel/marking)	35		→PMBD 6050
5A(p,s)	Si-P	=BC 807-16 (Typ-Code/Stempel/marking)	35		→BC 807
5AE 11	Si-N/P-Darl	4x NPN+1x PNP-Darl,-/80V, 2A, 2W	12-SIP	Rhm	—
5AG	Si-P/N	=HN3B01F-GR (Typ-Code/Stempel/marking)	46		→HN3B01F
5AM	Si-Di	=MMBD 6050 (Typ-Code/Stempel/marking)	35		→MMBD 6050
5AR	Si-P	=BC 807-16R (Typ-Code/Stempel/marking)	35		→BC 807
5AY	Si-P/N	=HN3B01F-Y (Typ-Code/Stempel/marking)	46		→HN3B01F
5B	Si-P	=BC 807-25W (Typ-Code/Stempel/marking)	35(2mm)		→BC 807W
5B	Si-N	=KST 4123 (Typ-Code/Stempel/marking)	35		→KST 4123
5B	Si-Di	=MA 707 (Typ-Code/Stempel/marking)	71 (2,7mm)		→MA 707
5B	Si-Di	=MA 733 (Typ-Code/Stempel/marking)	71 (1,7mm)		→MA 733
5B	Si-Di	=MMBD 6100 (Typ-Code/Stempel/marking)	35		→MMBD 6100
5B	Si-N	=MMBT 4123 (Typ-Code/Stempel/marking)	35		→MMBT 4123
5B	Si-Di	=PMBD 6100 (Typ-Code/Stempel/marking)	35		→PMBD 6100
5B(p,s)	Si-P	=BC 807-25 (Typ-Code/Stempel/marking)	35		→BC 807
5BM	Si-Di	=MMBD 6100 (Typ-Code/Stempel/marking)	35		→MMBD 6100
5BR	Si-P	=BC 807-25R (Typ-Code/Stempel/marking)	35		→BC 807
5C	Si-P	=BC 807-40W (Typ-Code/Stempel/marking)	35(2mm)		→BC 807W
5C	Si-Di	=MMBD 7000 (Typ-Code/Stempel/marking)	35		→MMBD 7000
5C	Si-Di	=PMBD 7000 (Typ-Code/Stempel/marking)	35		→PMBD 7000
5C	Si-N/P	=XN 4601 (Typ-Code/Stempel/marking)	46		→XN 4601
5C	Si-N/P	=XP 4601 (Typ-Code/Stempel/marking)	46(2mm)		→XP 4601
5C(p,s)	Si-P	=BC 807-40 (Typ-Code/Stempel/marking)	35		→BC 807
5CR	Si-P	=BC 807-40R (Typ-Code/Stempel/marking)	35		→BC 807
5D	Si-P	=BC 807W (Typ-Code/Stempel/marking)	35(2mm)		→BC 807W
5D	Si-Di	=FMMD 914 (Typ-Code/Stempel/marking)	35		→FMMD 914
5D	Si-Di	=HD 2A (Typ-Code/Stempel/marking)	35		→HS2A
5D	Si-Di	=MMBD 914 (Typ-Code/Stempel/marking)	35		→MMBD 914
5D	Si-Di	=MMSD 914 (Typ-Code/Stempel/marking)	71a(2,7mm)		→MMSD 914
5D	Si-Di	=PMBD 914 (Typ-Code/Stempel/marking)	35		→PMBD 914
5D(p)	Si-P	=BC 807 (Typ-Code/Stempel/marking)	35		→BC 807
5E	Si-P	=BC 808-16W (Typ-Code/Stempel/marking)	35(2mm)		→BC 808W
5E	Si-N	=FMMT-A43R (Typ-Code/Stempel/marking)	35		→FMMT-A43R
5E	Si-N/P	=XN 4608 (Typ-Code/Stempel/marking)	46		→XN 4608
5E	Si-P	=YTS 2908 (Typ-Code/Stempel/marking)	35		→YTS 2906
5E(p,s)	Si-P	=BC 808-16 (Typ-Code/Stempel/marking)	35		→BC 808
5ER	Si-P	=BC 608-16R (Typ-Code/Stempel/marking)	35		→BC 808
5EZ3,6...200D	Z-Di	3,6...200V, 5W, D5=5%, D10=10%	31a	Sie	BZV40/.., BZV48/.., 1N5334...5388
5F	Si-P	=BC 808-25W (Typ-Code/Stempel/marking)	35(2mm)		→BC 808W
5F	Si-Di	=MMBD 501 (Typ-Code/Stempel/marking)	35		→MMBD 501
5F	Si-N/P	=XN 4609 (Typ-Code/Stempel/marking)	46		→XN 4609
5F	Si-P	=YTS 2906A (Typ-Code/Stempel/marking)	35		→YTS 2906A
5F(p,s)	Si-P	=BC 808-25 (Typ-Code/Stempel/marking)	35		→BC 808
5FR	Si-P	=BC 608-25R (Typ-Code/Stempel/marking)	35		→BC 808
5G	Si-P	=BC 608-40W (Typ-Code/Stempel/marking)	35(2mm)		→BC 808W
5G	Si-Di	=MMBD 352 (Typ-Code/Stempel/marking)	35		→MMBD 352
5G(p,s)	Si-P	=BC 808-40 (Typ-Code/Stempel/marking)	35		→BC 808
5GR	Si-P	=BC 608-40R (Typ-Code/Stempel/marking)	35		→BC 808
5H	Si-P	=BC 808W (Typ-Code/Stempel/marking)	35(2mm)		→BC 608W
5H	Si-Di	=MMBD 701 (Typ-Code/Stempel/marking)	35		→MMBD 701
5H	Si-N	=XN 4501 (Typ-Code/Stempel/marking)	46		→XN 4501
5H	Si-N	=XP 4501 (Typ-Code/Stempel/marking)	46(2mm)		→XP 4501
5H(p)	Si-P	=BC 808 (Typ-Code/Stempel/marking)	35		→BC 808
5I	Si-N/P	=XN 4601 (Typ-Code/Stempel/marking)	46		→XN 4601
5I	Si-P	=YTS 4402 (Typ-Code/Stempel/marking)	35		→YTS 4402
5K	C-Di	=MMBV 809 (Typ-Code/Stempel/marking)	35		→MMBV 809
5K	Si-P	=XN 4401 (Typ-Code/Stempel/marking)	46		→XN 4401

ТИП	СТРУКТУРА	ХАРАКТЕРИСТИКИ	КОРПУС	ПРОИЗВОДИТЕЛЬ	АНАЛОГ
5K	Si-P	=XP4401 (Typ-Code/Stempel/marking)	46(2mm)		→XP4401
5KP5.0..110(A)	7-Di	TAZ, 5..110V, 5W	31a	Gie	BZW11/.., 1N5629..58, 1N6267..96
5L	C-Di	=MMBV609 (Typ-Code/Stempel/marking)	35		→MMBV609
5L	Si-N	=XN5501 (Typ-Code/Stempel/marking)	46		→XN5501
5L	Si-N	=XP5501 (Typ-Code/Stempel/marking)	46(2mm)		→XP5501
5M	Si-P	=IMBT3905 (Typ-Code/Stempel/marking)	35		→IMBT3905
5M	Si-N	=XN5531 (Typ-Code/Stempel/marking)	46		→XN5531
5M	Si-P	=YTS3905 (Typ-Code/Stempel/marking)	35		→YTS3905
5N	Si-P	=IMBT3906 (Typ-Code/Stempel/marking)	35		→IMBT3906
5N	Si-N	=XN6501 (Typ-Code/Stempel/marking)	46		→XN6501
5N	Si-N	=XP6501 (Typ-Code/Stempel/marking)	46(2mm)		→XP6501
5N	Si-P	=YTS4126 (Typ-Code/Stempel/marking)	35		→YTS4126
5O	Si-P	=XN6401 (Typ-Code/Stempel/marking)	46		→XN6401
5O	Si-P	=XP6401 (Typ-Code/Stempel/marking)	46(2mm)		→XP6401
5P	Si-P	=FMMT2907AR (Typ-Code/Stempel/marking)	35		→FMMT2907AR
5P	C-Di	=MA344 (Typ-Code/Stempel/marking)	46		→MA344
5P05M	50Hz-Thy	=5P1M: 50V	17e	Nec	T3,5N.., TAG661-.., TAG662-.., ++
5P1M	50Hz-Thy	100V, 5A(Tc=103°C), Igt/Ih <15/<10mA	17e	Nec	T3,5N.., TAG661-.., TAG662-.., ++
5P2M	50Hz-Thy	=5P1M: 200V	17e	Nec	T3,5N.., TAG661-.., TAG662-.., ++
5P4J(Z)	50Hz-Thy	400V, 5A(Tc=95°C), Igt/Ih <0,2/=1mA	30e	Nec	—
5P4M	50Hz-Thy	=5P1M: 400V	17e	Nec	T3,5N.., TAG661-.., TAG662-.., ++
5P5M	50Hz-Thy	=5P1M: 500V	17e	Nec	T3,5N.., TAG661-.., TAG662-.., ++
5P6J(Z)	50Hz-Thy	=5P4J: 600V	30e	Nec	—
5P6M	50Hz-Thy	=5P1M: 600V	17e	Nec	T3,5N.., TAG661-.., TAG662-.., ++
5Q	Si-N	=XN4502 (Typ-Code/Stempel/marking)	46		→XN4502
5R	Thy	=MMBS5060 (Typ-Code/Stempel/marking)	35		→MMB35060
5R	Si-N	=XN1501 (Typ-Code/Stempel/marking)	45		→XN1501
5R	Si-N	=XP1501 (Typ-Code/Stempel/marking)	45(2mm)		→XP1501
5S	Thy	=MMBS5061 (Typ-Code/Stempel/marking)	35		→MMB35061
5S	Si-N	=XN1504 (Typ-Code/Stempel/marking)	45		→XN1504
5S	Si-N	=XP1504 (Typ-Code/Stempel/marking)	45(2mm)		→XP1504
5S4M	F-Thy	400V, 5A(Tc=63°C), Igt <50/60mA, <5µs	17e	Nec	BT151/500, TAG6553-400, TAG6583-400
5T	Si-N	=BCW66RG (Typ-Code/Stempel/marking)	35		→BCW66RG
5T	Thy	=MMBS5062 (Typ-Code/Stempel/marking)	35		→MMB35062
5T	N-FET	=XN1871 (Typ-Code/Stempel/marking)	45		→XN1671
5U	MOS-N-FET-e	=XN1672 (Typ-Code/Stempel/marking)	45		→XN1672
5V	Si-P	=XN1401 (Typ-Code/Stempel/marking)	45		→XN1401
5V	Si-P	=XP1401 (Typ-Code/Stempel/marking)	45(2mm)		→XP1401
5W	Si-N	=XN2501 (Typ-Code/Stempel/marking)	45		→XN2501
5W	Si-N	=XP2501 (Typ-Code/Stempel/marking)	45(2mm)		→XP2501
5X	Si-N	=XN4504 (Typ-Code/Stempel/marking)	46		→XN4504
5Y	Si-N	=XN4503 (Typ-Code/Stempel/marking)	46		→XN4503
5Y1	Z-Di	=BZV49/C5V1 (Typ-Code/Stempel/marking)	39		→BZV49/C5V1
5Y6	Z-Di	=BZV49/C5V6 (Typ-Code/Stempel/marking)	39		→BZV49/C5V6
5Z	PUT	=MMBPU131 (Typ-Code/Stempel/marking)	35		→MMBPU131
5Z	Si-N+R	=XN6542 (Typ-Code/Stempel/marking)	46		→XN6542

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ТИП	СТРУКТУРА	ХАРАКТЕРИСТИКИ	КОРПУС	ПРОИЗВОДИТЕЛЬ	АНАЛОГ
6	C-Di	=HVU351 (Typ-Code/Stempel/marking)	71(1,7mm)		→HVU351
6.2B	Z-Di	=HZF6.2BP (Typ-Code/Stempel/marking)	71(5mm)		→HZF6.2BP
6.2C	Z-Di	=HZF6.2CP (Typ-Code/Stempel/marking)	71(5mm)		→HZF6.2CP
6.8B	Z-Di	=HZF6.8BP (Typ-Code/Stempel/marking)	71(5mm)		→HZF6.8BP
6.8C	Z-Di	=HZF6.8CP (Typ-Code/Stempel/marking)	71(5mm)		→HZF6.8CP
60	PIN-Di	=BAR60 (Typ-Code/Stempel/marking)	44		→BAR60
60	Si-N	=BFQ60 (Typ-Code/Stempel/marking)	52		→BFQ60
60024	Si-N	≈2N3055		Rca	→2N3055
60911	F-Thy	≈S3703SF	22a	Rca	→S3703SF
60912	F-Thy	≈S3702S	22a	Rca	→S3702S
60A..Y	Thy	=TAG60A..Y	7a	Tag	→TAG60A..Y
61	PIN-Di	=BAR61 (Typ-Code/Stempel/marking)	44		→BAR61
61A	N-FET	=MMBF4117 (Typ-Code/Stempel/marking)	35		→MMBF4117
61C	N-FET	=MMBF4116 (Typ-Code/Stempel/marking)	35		→MMBF4116
61E	N-FET	=MMBF4119 (Typ-Code/Stempel/marking)	35		→MMBF4119
61S	N-FET	=MMBF5456 (Typ-Code/Stempel/marking)	35		→MMBF5456
61U	N-FET	=MMBF5461 (Typ-Code/Stempel/marking)	35		→MMBF5461
62	Si-Di	=BAT62 (Typ-Code/Stempel/marking)	44		→BAT62

ТИП	СТРУКТУРА	ХАРАКТЕРИСТИКИ	КОРПУС	ПРОИЗВОДИТЕЛЬ	АНАЛОГ
62P	N-FET	=MMBFJ201 (Typ-Code/Stempel/marking)	35		→MMBFJ201
62Q	N-FET	=MMBFJ202 (Typ-Code/Stempel/marking)	35		→MMBFJ202
62W	N-FET	=MMBFJ211 (Typ-Code/Stempel/marking)	35		→MMBFJ211
62X	N-FET	=MMBFJ212 (Typ-Code/Stempel/marking)	35		→MMBFJ212
62Y	Z-Di	=BZV49/C62 (Typ-Code/Stempel/marking)	39		→BZV49/C62
63(s)	Si-Di	=BAT64 (Typ-Code/Stempel/marking)	35		→BAT64
636BC/A	Si-P	=BCX51	39b	Phi	→BCX51
636BC/B	Si-P	=BCX52	39b	Phi	→BCX52
636BC/C	Si-P	=BCX53	39b	Phi	→BCX53
637BC/A	Si-N	=BCX54	39b	Phi	→BCX54
637BC/B	Si-N	=BCX55	39b	Phi	→BCX55
637BC/C	Si-N	=BCX56	39b	Phi	→BCX56
64(s)	Si-Di	=BAT64-04 (Typ-Code/Stempel/marking)	35		→BAT64-04
645	Si-N	=BFQ645 (Typ-Code/Stempel/marking)	51		→BFQ645
65(s)	Si-Di	=BAT64-05 (Typ-Code/Stempel/marking)	35		→BAT64-05
66(s)	Si-Di	=BAT64-06 (Typ-Code/Stempel/marking)	35		→BAT64-06
67	Si-N	=BFP67 (Typ-Code/Stempel/marking)	44		→BFP67
67(s)	Si-Di	=BAT64-07 (Typ-Code/Stempel/marking)	44		→BAT67-07
68Y	Z-Di	=BZV49/C68 (Typ-Code/Stempel/marking)	39		→BZV49/C68
6A	Si-N	=BC617-16W (Typ-Code/Stempel/marking)	35(2mm)		→BC817W
6A	C-Di	=MA321 (Typ-Code/Stempel/marking)	71 (2,7mm)		→MA321
6A	C-Di	=MA360 (Typ-Code/Stempel/marking)	71 (1,7mm)		→MA360
6A	N-FET	=MMBF4416 (Typ-Code/Stempel/marking)	35		→MMBF4416
6A	Si-P+R	=MUN2111 (Typ-Code/Stempel/marking)	35		→MUN2111
6A	Si-P+R	=MUN5111 (Typ-Code/Stempel/marking)	35(2mm)		→MUN5111
6A	Si-P+R	=UN2111 (Typ-Code/Stempel/marking)	35		→UN2111
6A	Si-P+R	=UN5111 (Typ-Code/Stempel/marking)	35(2mm)		→UN5111
6A	Si-P+R	=UN9111 (Typ-Code/Stempel/marking)	35(1,6mm)		→UN9111
6A(p,s)	Si-N	=BC817-16 (Typ-Code/Stempel/marking)	35		→BC817
6AM11	MOS-P/N-FET*	=3x2SJ172+3x2SK970: 5A, 36W	12-SIP	Hit	—
6AM12	MOS-P/N-FET*	=3x2SJ172+3x2SK970: 7A, 42W	12-SIL	Hit	—
6AM13	MOS-P/N-FET*	=3x2SJ173+3x2SK971: 10A, 42W	12-SIL	Hit	—
6AM14	MOS-P/N-FET*	3xP+3xNV-MOS, LogL, 60V, 7A, 42W	12-SIL	Hit	—
6AR	Si-N	=BC617-16R (Typ-Code/Stempel/marking)	35		→BC817
6B	Si-N	=BC617-25W (Typ-Code/Stempel/marking)	35(2mm)		→BC817W
6B	C-Di	=MA329 (Typ-Code/Stempel/marking)	71 (2,7mm)		→MA329
6B	C-Di	=MA361 (Typ-Code/Stempel/marking)	71 (1,7mm)		→MA361
6B	N-FET	=MMBF5464 (Typ-Code/Stempel/marking)	35		→MMBF5464
6B	Si-P+R	=MUN2112 (Typ-Code/Stempel/marking)	35		→MUN2112
6B	Si-P+R	=MUN5112 (Typ-Code/Stempel/marking)	35(2mm)		→MUN5112
6B	Si-P+R	=UN2112 (Typ-Code/Stempel/marking)	35		→UN2112
6B	Si-P+R	=UN5112 (Typ-Code/Stempel/marking)	35(2mm)		→UN5112
6B	Si-P+R	=UN9112 (Typ-Code/Stempel/marking)	35(1,6mm)		→UN9112
6B(p,s)	Si-N	=BC817-25 (Typ-Code/Stempel/marking)	35		→BC817
6BR	Si-N	=BC817-25R (Typ-Code/Stempel/marking)	35		→BC817
6C	Si-N	=BC617-40W (Typ-Code/Stempel/marking)	35(2mm)		→BC617W
6C	C-Di	=MA333 (Typ-Code/Stempel/marking)	71(2,7mm)		→MA333
6C	N-FET	=MMBFU310 (Typ-Code/Stempel/marking)	35		→MMBFU310
6C	Si-P+R	=MUN2113 (Typ-Code/Stempel/marking)	35		→MUN2113
6C	Si-P+R	=MUN5113 (Typ-Code/Stempel/marking)	35(2mm)		→MUN5113
6C	Si-P+R	=UN2113 (Typ-Code/Stempel/marking)	35		→UN2113
6C	Si-P+R	=UN5113 (Typ-Code/Stempel/marking)	35(2mm)		→UN5113
6C	Si-P+R	=UN9113 (Typ-Code/Stempel/marking)	35(1,6mm)		→UN9113
6C(p,s)	Si-N	=BC617-40 (Typ-Code/Stempel/marking)	35		→BC617
6CR	Si-N	=BC817-40R (Typ-Code/Stempel/marking)	35		→BC617
6D	C-Di	=MA334 (Typ-Code/Stempel/marking)	71(2,7mm)		→MA334
6D	C-Di	=MA363 (Typ-Code/Stempel/marking)	71(1,7mm)		→MA363
6D	N-FET	=MMBF5457 (Typ-Code/Stempel/marking)	35		→MMBF5457
6D	Si-P+R	=MUN2114 (Typ-Code/Stempel/marking)	35		→MUN2114
6D	Si-P+R	=MUN5114 (Typ-Code/Stempel/marking)	35(2mm)		→MUN5114
6D	Si-P+R	=UN2114 (Typ-Code/Stempel/marking)	35		→UN2114
6D	Si-P+R	=UN5114 (Typ-Code/Stempel/marking)	35(2mm)		→UN5114
6D	Si-P+R	=UN9114 (Typ-Code/Stempel/marking)	35(1,6mm)		→UN9114
6D(p)	Si-P	=BC817 (Typ-Code/Stempel/marking)	35		→BC817
6E	Si-N	=BC818-16W (Typ-Code/Stempel/marking)	35(2mm)		→BC616W
6E	Si-P	=FMMT-A93R (Typ-Code/Stempel/marking)	35		→FMMT-A93R

ТИП	СТРУКТУРА	ХАРАКТЕРИСТИКИ	КОРПУС	ПРОИЗВОДИТЕЛЬ	АНАЛОГ
6E	C-Di	=MA335 (Typ-Code/Stempel/marking)	71(2,7mm)		→MA335
6E	C-Di	=MA364 (Typ-Code/Stempel/marking)	71(1,7mm)		→MA364
6E	P-FET	=MMBF5460 (Typ-Code/Stempel/marking)	35		→MMBF5460
6E	Si-P+R	=MUN2115 (Typ-Code/Stempel/marking)	35		→MUN2115
6E	Si-P+R	=MUN5115 (Typ-Code/Stempel/marking)	35(2mm)		→MUN5115
6E	Si-P+R	=UN2115 (Typ-Code/Stempel/marking)	35		→UN2115
6E	Si-P+R	=UN5115 (Typ-Code/Stempel/marking)	35(2mm)		→UN5115
6E	Si-P+R	=UN9115 (Typ-Code/Stempel/marking)	35(1,6mm)		→UN9115
6E(p,s)	Si-N	=BC818-16 (Typ-Code/Stempel/marking)	35		→BC818
6ER	Si-N	=BC818-16R (Typ-Code/Stempel/marking)	35		→BC818
6F	Si-N	=BC818-25W (Typ-Code/Stempel/marking)	35(2mm)		→BC818W
6F	C-Di	=MA337 (Typ-Code/Stempel/marking)	71(2,7mm)		→MA337
6F	C-Di	=MA365 (Typ-Code/Stempel/marking)	71(1,7mm)		→MA365
6F	N-FET	=MMBF4860 (Typ-Code/Stempel/marking)	35		→MMBF4860
6F	Si-P+R	=MUN2116 (Typ-Code/Stempel/marking)	35		→MUN2116
6F	Si-P+R	=MUN5116 (Typ-Code/Stempel/marking)	35(2mm)		→MUN5116
6F	Si-P+R	=UN2116 (Typ-Code/Stempel/marking)	35		→UN2116
6F	Si-P+R	=UN5116 (Typ-Code/Stempel/marking)	35(2mm)		→UN5116
6F	Si-P+R	=UN9116 (Typ-Code/Stempel/marking)	35(1,6mm)		→UN9116
6F(p,s)	Si-N	=BC818-25 (Typ-Code/Stempel/marking)	35		→BC818
6FR	Si-N	=BC818-25R (Typ-Code/Stempel/marking)	35		→BC818
6G	Si-N	=BC818-40W (Typ-Code/Stempel/marking)	35(2mm)		→BC818W
6G	N-FET	=MMBF4393 (Typ-Code/Stempel/marking)	35		→MMBF4393
6G	Si-P+R	=MUN2130 (Typ-Code/Stempel/marking)	35		→MUN2130
6G	Si-P+R	=MUN5130 (Typ-Code/Stempel/marking)	35(2mm)		→MUN5130
6G	N-FET	=PMBF4393 (Typ-Code/Stempel/marking)	35		→PMBF4393
6G(p,s)	Si-N	=BC818-40 (Typ-Code/Stempel/marking)	35		→BC818
6GR	Si-N	=BC818-40R (Typ-Code/Stempel/marking)	35		→BC818
6H	Si-N	=BC818W (Typ-Code/Stempel/marking)	35(2mm)		→BC818W
6H	C-Di	=MA338 (Typ-Code/Stempel/marking)	71(2,7mm)		→MA338
8H	C-Di	=MA366 (Typ-Code/Stempel/marking)	71(1,7mm)		→MA366
6H	N-FET	=MMBF5486 (Typ-Code/Stempel/marking)	35		→MMBF5486
6H	Si-P+R	=MUN2131 (Typ-Code/Stempel/marking)	35		→MUN2131
8H	Si-P+R	=MUN5131 (Typ-Code/Stempel/marking)	35(2mm)		→MUN5131
8H	Si-P+R	=UN2117 (Typ-Code/Stempel/marking)	35		→UN2117
8H	Si-P+R	=UN5117 (Typ-Code/Stempel/marking)	35(2mm)		→UN5117
6H	Si-P+R	=UN9117 (Typ-Code/Stempel/marking)	35(1,6mm)		→UN9117
6H(p)	Si-N	=BC818 (Typ-Code/Stempel/marking)	35		→BC818
6I	Si-P+R	=UN2118 (Typ-Code/Stempel/marking)	35		→UN2118
6I	Si-P+R	=UN5118 (Typ-Code/Stempel/marking)	35(2mm)		→UN5118
6I	Si-P+R	=UN9118 (Typ-Code/Stempel/marking)	35(1,6mm)		→UN9118
6J	N-FET	=MMBF4391 (Typ-Code/Stempel/marking)	35		→MMBF4391
8J	Si-P+R	=MUN2132 (Typ-Code/Stempel/marking)	35		→MUN2132
8J	Si-P+R	=MUN5132 (Typ-Code/Stempel/marking)	35(2mm)		→MUN5132
6J	N-FET	=PMBF4391 (Typ-Code/Stempel/marking)	35		→PMBF4391
6K	C-Di	=MA341 (Typ-Code/Stempel/marking)	71(2,7mm)		→MA341
6K	C-Di	=MA367 (Typ-Code/Stempel/marking)	71(1,7mm)		→MA367
8K	N-FET	=MMBF4392 (Typ-Code/Stempel/marking)	35		→MMBF4392
6K	Si-P+R	=MUN2133 (Typ-Code/Stempel/marking)	35		→MUN2133
6K	Si-P+R	=MUN5133 (Typ-Code/Stempel/marking)	35(2mm)		→MUN5133
6K	N-FET	=PMBF4392 (Typ-Code/Stempel/marking)	35		→PMBF4392
6K	Si-P+R	=UN2119 (Typ-Code/Stempel/marking)	35		→UN2119
8K	Si-P+R	=UN5119 (Typ-Code/Stempel/marking)	35(2mm)		→UN5119
8K	Si-P+R	=UN9119 (Typ-Code/Stempel/marking)	35(1,6mm)		→UN9119
6L	C-Di	=MA366 (Typ-Code/Stempel/marking)	71(1,7mm)		→MA368
8L	N-FET	=MMBF5459 (Typ-Code/Stempel/marking)	35		→MMBF5459
6L	Si-P+R	=MUN2134 (Typ-Code/Stempel/marking)	35		→MUN2134
6L	Si-P+R	=MUN5134 (Typ-Code/Stempel/marking)	35(2mm)		→MUN5134
6L	Si-P+R	=UN2110 (Typ-Code/Stempel/marking)	35		→UN2110
6L	Si-P+R	=UN5110 (Typ-Code/Stempel/marking)	35(2mm)		→UN5110
6L	Si-P+R	=UN9110 (Typ-Code/Stempel/marking)	35(1,6mm)		→UN9110
6M	N-FET	=MMBF5485 (Typ-Code/Stempel/marking)	35		→MMBF5485
8M	Si-P+R	=UN211D (Typ-Code/Stempel/marking)	35		→UN211D
8M	Si-P+R	=UN511D (Typ-Code/Stempel/marking)	35(2mm)		→UN511D
8M	Si-P+R	=UN911D (Typ-Code/Stempel/marking)	35(1,6mm)		→UN911D
6N	C-Di	=MA339 (Typ-Code/Stempel/marking)	71(2,7mm)		→MA339

ТИП	СТРУКТУРА	ХАРАКТЕРИСТИКИ	КОРПУС	ПРОИЗВОДИТЕЛЬ	АНАЛОГ
6N	C-Di	=MA372 (Typ-Code/Stempel/marking)	71(1,7mm)		→MA372
6N	Si-P+R	=UN211E (Typ-Code/Stempel/marking)	35		→UN211E
6N	Si-P+R	=UN511E (Typ-Code/Stempel/marking)	35(2mm)		→UN511E
6N	Si-P+R	=UN911E (Typ-Code/Stempel/marking)	35(1,6mm)		→UN911E
6O	Si-P+R	=UN211F (Typ-Code/Stempel/marking)	35		→UN211F
6O	Si-P+R	=UN511F (Typ-Code/Stempel/marking)	35(2mm)		→UN511F
6O	Si-P+R	=UN911F (Typ-Code/Stempel/marking)	35(1,6mm)		→UN911F
6P	Si-P	=BCX71RH (Typ-Code/Stempel/marking)	35		→BCX71RH
6P	N-FET	=MMBFJ111 (Typ-Code/Stempel/marking)	35		→MMBFJ111
6P	Si-P+R	=UN211H (Typ-Code/Stempel/marking)	35		→UN211H
6P	Si-P+R	=UN511H (Typ-Code/Stempel/marking)	35(2mm)		→UN511H
6P	Si-P+R	=UN911H (Typ-Code/Stempel/marking)	35(1,6mm)		→UN911H
6Q	Si-P+R	=UN211L (Typ-Code/Stempel/marking)	35		→UN211L
6Q	Si-P+R	=UN511L (Typ-Code/Stempel/marking)	35(2mm)		→UN511L
6Q	Si-P+R	=UN911L (Typ-Code/Stempel/marking)	35(1,6mm)		→UN911L
6R	N-FET	=MMBFJ112 (Typ-Code/Stempel/marking)	35		→MMBFJ112
6R	Si-P+R	=XN4112 (Typ-Code/Stempel/marking)	46		→XN4112
6R	Si-P+R	=XP4112 (Typ-Code/Stempel/marking)	46(2mm)		→XP4112
6S	C-Di	=MA353 (Typ-Code/Stempel/marking)	71(2,7mm)		→MA353
6S	C-Di	=MA371 (Typ-Code/Stempel/marking)	71(1,7mm)		→MA371
6S	N-FET	=MMBFJ113 (Typ-Code/Stempel/marking)	35		→MMBFJ113
6S	Si-P+R	=UN5101 (Typ-Code/Stempel/marking)	35(2mm)		→UN5101
6S	Si-P+R	=XN4113 (Typ-Code/Stempel/marking)	46		→XN4113
6S	Si-P+R	=XP4113 (Typ-Code/Stempel/marking)	46(2mm)		→XP4113
6T	Si-P	=BCW66RG (Typ-Code/Stempel/marking)	35		→BCW68RG
6T	C-Di	=MA331 (Typ-Code/Stempel/marking)	71(1,7mm)		→MA331
6T	N-FET	=MMBFJ310 (Typ-Code/Stempel/marking)	35		→MMBFJ310
6T	Si-P+R	=XN4115 (Typ-Code/Stempel/marking)	46		→XN4115
6T	Si-P+R	=XP4115 (Typ-Code/Stempel/marking)	46(2mm)		→XP4115
6U	C-Di	=MA332 (Typ-Code/Stempel/marking)	71(1,7mm)		→MA332
6U	N-FET	=MMBFJ309 (Typ-Code/Stempel/marking)	35		→MMBFJ309
6U	Si-P+R	=XN4116 (Typ-Code/Stempel/marking)	46		→XN4116
6U	Si-P+R	=XP4116 (Typ-Code/Stempel/marking)	46(2mm)		→XP4116
6V	Si-P+R	=XN6112 (Typ-Code/Stempel/marking)	46		→XN6112
6V	Si-P+R	=XP6112 (Typ-Code/Stempel/marking)	46(2mm)		→XP6112
6W	P-FET	=MMBFJ175 (Typ-Code/Stempel/marking)	35		→MMBFJ175
6W	Si-P+R	=XN6113 (Typ-Code/Stempel/marking)	46		→XN6113
6W	Si-P+R	=XP6113 (Typ-Code/Stempel/marking)	46(2mm)		→XP6113
6X	P-FET	=MMBFJ176 (Typ-Code/Stempel/marking)	35		→MMBFJ176
6X	Si-P+R	=XN6115 (Typ-Code/Stempel/marking)	46		→XN6115
6X	Si-P+R	=XP6115 (Typ-Code/Stempel/marking)	46(2mm)		→XP6115
6Y	C-Di	=MA355 (Typ-Code/Stempel/marking)	71(1,7mm)		→MA355
6Y	P-FET	=MMBFJ177 (Typ-Code/Stempel/marking)	35		→MMBFJ177
6Y	Si-P+R	=XN6116 (Typ-Code/Stempel/marking)	46		→XN6116
6Y	Si-P+R	=XP6116 (Typ-Code/Stempel/marking)	46(2mm)		→XP6116
6Y2	Z-Di	=BZV49/C6V2 (Typ-Code/Stempel/marking)	39		→BZV49/C6V2
6Y8	Z-Di	=BZV49/C6V8 (Typ-Code/Stempel/marking)	39		→BZV49/C6V8
6Z	C-Di	=MA373 (Typ-Code/Stempel/marking)	71(1,7mm)		→MA373
6Z	N-FET	=MMBF170 (Typ-Code/Stempel/marking)	35		→MMBF170
6Z	Si-P+R	=XN6111 (Typ-Code/Stempel/marking)	46		→XN6111
6Z	Si-P+R	=XP6111 (Typ-Code/Stempel/marking)	46(2mm)		→XP6111
7		**7**			
7	C-Di	=HVU307 (Typ-Code/Stempel/marking)	71(1,7mm)		→HVU307
7.5B	Z-Di	=HZF7.5BP (Typ-Code/Stempel/marking)	71(5mm)		→HZF7.5BP
7.5C	Z-Di	=HZF7.5CP (Typ-Code/Stempel/marking)	71(5mm)		→HZF7.5CP
70	Si-N	=BFQ70 (Typ-Code/Stempel/marking)	51		→BFQ70
702	MOS-N-FET-e	=2N7002 (Typ-Code/Stempel/marking)	35		→2N7002
70HF-10..100	Si-Di	Gl-L, 100..1000V, 70A	32a	Mot	OS75-..
70HF-10R..100R	Si-Di	=HF70..	32b		—
71	Si-N	=BFQ71 (Typ-Code/Stempel/marking)	51		→BFQ71
71T2	Si-N	NF/S-L, 80V, 2A, 15W, 50MHz, B>30	43g	Tho	(BD379, 2SC3252, 2SD1177..1178,++)
72	MOS-N-FET-e	=2N7002 (Typ-Code/Stempel/marking)	35		→2N7002
72	Si-N	=BFQ72 (Typ-Code/Stempel/marking)	51		→BFQ72
72T2	Si-N	=71T2: B>75	43g	Tho	(BD379, 2SC3252, 2SD1177..1178,++)
73(s,p)	Si-Di	=BAS70 (Typ-Code/Stempel/marking)	35		→BAS70

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73S	Si-N	=BFQ 73 (Typ-Code/Stempel/marking)	51		→BFQ73
73T2	Si-N	NF/S-L, 80V, 1A, 15W, B>30	43g	Tho	(BD139, BD230, BD379, 2SC3252,++)
74	Si-N	=BFQ 74 (Typ-Code/Stempel/marking)	51		→BFQ74
74(s,p)	Si-Di	=BAS 70-04 (Typ-Code/Stempel/marking)	35		→BAS 70-04
7400	CMOS/TTL	Quad 2-Input NAND Gate	14-DIP		—
7400	Logic		20-MP		—
7400/2	TTL-Logic	Quad 2-Input NAND Gate	14-DIP		—
7401	CMOS/TTL	Quad 2-Input NAND Gate	14-DIP		—
7401	Logic		20-MP		—
7401/2	TTL-Logic	Quad 2-Input NAND Gate	14-DIP		—
7401/3	TTL-Logic	Quad 2-Input NAND Gate	14-DIP		—
7401/3	TTL-Logic		20-MP		—
7402	CMOS/TTL	Quad 2-Input NOR Gate	14-DIP		—
7402	Logic		20-MP		—
7402/2	TTL-Logic	Quad 2-Input NOR Gate	14-DIP		—
7403	CMOS/TTL	Quad 2-Input NAND Gate	14-DIP		—
7403	Logic		20-MP		—
7404	CMOS/TTL	Hex Inverter	14-DIP		—
7404	Logic		20-MP		—
7404/2	TTL-Logic	Hex Inverter	14-DIP		—
7405	CMOS/TTL	Hex Inverter	14-DIP		—
7405	Logic		20-MP		—
7405/2	TTL-Logic	Hex Inverter	14-DIP		—
7406	CMOS/TTL	Hex Driver, inverting (30V)	14-DIP		—
7407	Logic	Hex Driver, non inverting	14-DIP		—
7408	CMOS/TTL	Quad 2-Input AND Gate	14-DIP		—
7408	Logic		20-MP		—
7409	CMOS/TTL	Quad 2-Input AND Gate	14-DIP		—
7409	Logic		20-MP		—
7410	CMOS/TTL	Triple 3-Input NAND Gate	14-DIP		—
7410	Logic		20-MP		—
7410/2	TTL-Logic	Triple 3-Input NAND Gate	14-DIP		—
74100	TTL-Logic	Dual 4-Bit D-Latch, non inverting	24-DIP		—
741000	TTL-Logic	Quad 2-Input Buffered NAND Gates	14-DIP		—
741000	TTL-Logic		20-MP		—
741002	TTL-Logic	Quad 2-Input Buffered NOR Driver	14-DIP		—
741002	TTL-Logic		20-MP		—
741003	TTL-Logic	Quad 2-Input Buffered NAND Gates	14-DIP		—
741003	TTL-Logic		20-MP		—
741004	TTL-Logic	Hex Buffered Inverter	14-DIP		—
741004	TTL-Logic		20-MP		—
741005	TTL-Logic	Hex Buffered Inverter	14-DIP		—
741005	TTL-Logic		20-MP		—
741008	TTL-Logic	Quad 2-Input Buffered AND Driver	14-DIP		—
741008	TTL-Logic		20-MP		—
74101/1	TTL-Logic	Negative Edge Triggered JK Flip-Flop	14-DIP		—
74101/1	TTL-Logic	with AND/OR Inputs and Preset			—
74101/2	TTL-Logic	Negative Edge Triggered JK Flip-Flop	14-DIP		—
74101/2	TTL-Logic	with AND/OR Inputs and Preset			—
741010	TTL-Logic	Triple 3-Input Buffered NAND Gate	14-DIP		—
741010	TTL-Logic		20-MP		—
741011	TTL-Logic	Triple 3-Input Buffered AND Gate	14-DIP		—
741011	TTL-Logic		20-MP		—
741016	TTL-Logic	16-Bit Bus Termination Array	24-DIP		—
741018	TTL-Logic	18-Bit Bus Termination Array	24-DIP		—
74102/1	TTL-Logic	Positive Edge Triggered JK Flip-Flop	14-DIP		—
74102/1	TTL-Logic	with AND Inputs, Preset and Clear			—
74102/2	TTL-Logic	Positive Edge Triggered JK Flip-Flop	14-DIP		—
74102/2	TTL-Logic	with AND Inputs, Preset and Clear			—
741020	TTL-Logic	Dual 4-Input Buffered NAND Gate	14-DIP		—
741020	TTL-Logic		20-MP		—
74103	TTL-Logic	Dual Negative Edge Triggered JK	14-DIP		—
74103	TTL-Logic	Flip-Flops with Clear			—
741032	TTL-Logic	Quad 2-Input Buffered OR Gate	14-DIP		—
741032	TTL-Logic		20-MP		—
741034	TTL-Logic	Hex Driver, non inverting	14-DIP		—

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741034	TTL-Logic		20-MP		—
741035	TTL-Logic	Hex buffer, non inverting	14-DIP		—
741035	TTL-Logic		20-MP		—
741036	TTL-Logic	Quad 2-Input Buffered NOR Driver	14-DIP		—
741036	TTL-Logic		20-MP		—
74104	TTL-Logic	3-Input Negative Pulse Triggered JK	14-DIP		—
74104	TTL-Logic	Flip-Flop with Preset and Claar			—
74105	TTL-Logic	3-Input Negative Pulse Triggered JK	14-DIP		—
74105	TTL-Logic	Flip-Flop with Preset and Clear			—
741050	TTL-Logic	12-Bit Bus Termination Array	16-DIP		—
741051	TTL-Logic	12-Bit Bus Termination Array	16-DIP		—
741052	TTL-Logic	16-Bit Bus Termination Array	20-DIP		—
741053	TTL-Logic	16-Bit Bus Termination Array	20-DIP		—
741056	TTL-Logic	8-Bit Bua Termination Array	16-DIP		—
74106	TTL-Logic	Dual Negative Edge Triggered JK	14-DIP		—
74106	TTL-Logic	Flip-Flop with Preset and Clear			—
74107	CMOS/TTL	Dual JK Flip-Flop with Claar	14-DIP		—
74107	Logic		20-MP		—
74108	CMOS/TTL	Dual Nagative Edge Trigg. JK	14-DIP		—
74106	Logic	Flip-Flop with Common Preset, Claar,			—
74108		Clock			—
74109	CMOS/TTL	Dual Positive Edge Triggered JK	16-DIP		—
74109	Logic	Flip-Flop with Preset and Clear	20-MP		—
7411	CMOS/TTL	Triple 3-Input AND Gate	14-DIP		—
7411	Logic		20-MP		—
7411/2	TTL-Logic	Triple 3-Input AND Gate	14-DIP		—
74110	TTL-Logic	Positive Pulse Triggered JK Flip-Flop	14-DIP		—
74110	TTL-Logic	with Preset, Clear and Inputlock			—
7411000	CMOS-Logic	Quad 2-Input NAND Gate	14-DIP		—
7411000	CMOS-Logic		20-MP		—
7411002	CMOS-Logic	Quad 2-Input NOR Gate	14-DIP		—
7411002	CMOS-Logic		20-MP		—
7411008	CMOS-Logic	Quad 2-Input AND Gate	14-DIP		—
7411008	CMOS-Logic		20-MP		—
7411010	CMOS-Logic	Tripla 3-Input NAND Gate	14-DIP		—
7411010	CMOS-Logic		20-MP		—
7411011	CMOS-Logic	Triple 3-Input AND Gate	14-DIP		—
7411011	CMOS-Logic		20-MP		—
7411020	CMOS-Logic	Dual 4-Input NAND Gate	14-DIP		—
7411020	CMOS-Logic		20-MP		—
7411021	CMOS-Logic	Dual 4-Input AND Gate	14-DIP		—
7411021	CMOS-Logic		20-MP		—
7411027	CMOS-Logic	Triple 3-Input NOR Gate	14-DIP		—
7411027	CMOS-Logic		20-MP		—
7411030	CMOS-Logic	8-Input NAND Gate	14-DIP		—
7411030	CMOS-Logic		20-MP		—
7411032	CMOS-Logic	Quad 2-Input OR Gata	14-DIP		—
7411032	CMOS-Logic		20-MP		—
7411074	CMOS-Logic	Dual D-Flip-Flop with Complementary	14-DIP		—
7411074	CMOS-Logic	Outputs With Preset and Clear	20-MP		—
74111	TTL-Logic	Dual Positive Pulse Trig. JK	16-DIP		—
74111	TTL-Logic	Flip-Flops with Preset, Clear and			—
74111	TTL-Logic	Inputlock			—
7411109	CMOS-Logic	Dual Positive Edga Triggared JK	14-DIP		—
7411109	CMOS-Logic	Flip-Flop with Preset and Clear	20-MP		—
74112	CMOS/TTL	Dual Negative Edge Triggared JK	16-DIP		—
74112	Logic	Flip-Flop with Preset and Clear	20-MP		—
7411240	CMOS-Logic	Octal Bus Line Driver, inverting	24-DIP		—
7411240	CMOS-Logic		26-MP		—
7411241	CMOS-Logic	Octel Bus Line Driver, non inverting	24-DIP		—
7411241	CMOS-Logic		28-MP		—
7411244	CMOS-Logic	Octel Bus Line Driver, non inverting	24-DIP		—
7411244	CMOS-Logic		28-MP		—
7411245	CMOS-Logic	Quad Bus Transceiver, non inverting	24-DIP		—
7411245	CMOS-Logic		28-MP		—
74113	CMOS/TTL	Dual Negative Edge Triggered JK	14-DIP		—

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74113	Logic	Flip-Flop with Preset	20-MP		—
7411373	CMOS-Logic	8-Bit D-Latch with Enable, non	24-DIP		—
7411373	CMOS-Logic	inverting	28-MP		—
7411374	CMOS-Logic	8-Bit D-Register with Enable, non	24-DIP		—
7411374	CMOS-Logic	inverting	28-MP		—
74114	CMOS/TTL	Dual Negative Edge Triggered JK	14-DIP		—
74114	Logic	Flip-Flop with Preset and Clear	20-MP		—
74115	TTL-Logic	Dual Pulse Triggered JK Flip-Flops	14-DIP		—
74115	TTL-Logic	with Clear and Inputlock			—
7411520	CMOS-Logic	8-Bit Comparator, inverting Output	24-DIP		—
7411520	CMOS-Logic		28-MP		—
7411521	CMOS-Logic	8-Bit Comparator, inverting Output	20-DIP		—
7411521	CMOS-Logic		20-MP		—
7411533	CMOS-Logic	8-Bit D-Latch with Enable, inverting	20-DIP		—
7411533	CMOS-Logic		20-MP		—
7411534	CMOS-Logic	8-Bit D-Latch with Enable, inverting	24-DIP		—
7411534	CMOS-Logic		28-MP		—
74116	TTL-Logic	Dual 4-Bit Latch with Clear, non	24-DIP		—
74116	TTL-Logic	inverting			—
7411620	CMOS-Logic	8-Bit Bi-Directional Bus Driver with	24-DIP		—
7411620	CMOS-Logic	Register, inverting	28-MP		—
7411623	CMOS-Logic	8-Bit Bi-Directional Bus Transceiver	24-DIP		—
7411623	CMOS-Logic	with Register, non inverting	28-MP		—
7411640	CMOS-Logic	8-Bit Bi-Directional Bus Transceiver,	24-DIP		—
7411640	CMOS-Logic	inverting	28-MP		—
7411643	CMOS-Logic	8-Bit Bi-Directional Bus Transceiver,	24-DIP		—
7411643	CMOS-Logic	inverting/non inverting	28-MP		—
7411646	CMOS-Logic	8-Bit Bus-Transceiver with	24-DIP		—
7411646	CMOS-Logic	Bi-Directional Registers, non	28-MP		—
7411646		inverting			—
74118	TTL-Logic	Hex RS Flip-Flop with Common	16-DIP		—
74118	TTL-Logic	Reset-Input			—
741181	TTL-Logic	4-Bit Arithmetic/Logic Unit, Function	24-DIP		—
741181	TTL-Logic	Generator	28-MP		—
74119	TTL-Logic	Hex RS Flip-Flop with Separate Reset	24-DIP		—
74119	TTL-Logic	Input and Master Reset			—
7412	CMOS/TTL	Triple 3-Input NAND Gate	14-DIP		—
7412	Logic				—
74120	TTL-Logic	Dual Pulse Synchronizer/Driver	16-DIP		—
74121	TTL-Logic	Monoflop with Schmitt Trigger Input	14-DIP		—
74122	TTL-Logic	Post-Triggerable Monoflop with Clear	14-DIP		—
74122	TTL-Logic		20-MP		—
74123	CMOS/TTL	Dual Post-Triggerable Monoflop with	16-DIP		—
74123	Logic	Clear	20-MP		—
74124/1	TTL-Logic	Dual Voltage Controlled Oscillator	16-DIP		—
74124/1	TTL-Logic		20-MP		—
74124/2	TTL-Logic	Dual Voltege-Controlled Oscillator	14-DIP		—
741240	TTL-Logic	Octal Bus Line Driver, inverting	20-DIP		—
741240	TTL-Logic		20-MP		—
741241	TTL-Logic	Octal Bus Line Driver, non inverting	20-DIP		—
741241	TTL-Logic		20-MP		—
741242	TTL-Logic	Quad Bi-Directional Bus Transceiver,	20-DIP		—
741242	TTL-Logic	inverting	20-MP		—
741243	TTL-Logic	Quad Bus Transceiver, non inverting	14-DIP		—
741243	TTL-Logic		20-MP		—
741244	TTL-Logic	Octal Bus Line Driver, non inverting	20-DIP		—
741244	TTL-Logic		20-MP		—
741245	TTL-Logic	Quad Bus Transceiver, non inverting	20-DIP		—
741245	TTL-Logic		20-MP		—
74125	CMOS/TTL	Quad Bus Line Driver, non inverting	14-DIP		—
74125	Logic		20-MP		—
74126	CMOS/TTL	Quad Bus Line Driver, non inverting	14-DIP		—
74126	Logic		20-MP		—
74128	TTL-Logic	Quad 2-Input 50-Ohm-NOR Power-Driver	14-DIP		—
7413	CMOS/TTL	Dual 4-Input NAND Schmitt Trigger	14-DIP		—
7413	Logic				—

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74130	TTL-Logic	Quad 2-Input AND Driver (30V)	14-DIP		—
74131	CMOS/TTL	Quad 2-Input AND Driver (15V)	16-DIP		—
7413t	Logic		20-MP		—
7413t/1	TTL-Logic	3-Bit Binery Decoder/Demultiplexer	14-DIP		—
7413t/1	TTL-Logic	with Address Register	20-MP		—
74132	CMOS/TTL	Quad 2-Input NAND Schmitt Trigger	14-DIP		—
74132	Logic		20-MP		—
74133	CMOS/TTL	13-Input NAND Gate	t6-DIP		—
74t33	Logic		20-MP		—
74t34	TTL-Logic	t2-Input NAND Gate	14-DIP		—
74t34	TTL-Logic		20-MP		—
74135	TTL-Logic	Quad 2-Input EX-NOR/OR Gate	t6-DIP		—
74t35	TTL-Logic		20-MP		—
74136	TTL-Logic	Quad 2-Input EX-OR Gate	t4-DIP		—
74136	TTL-Logic		20-MP		—
74137	CMOS/TTL	3-Bit Binary Decoder/Demultiplexer w.	16-DIP		—
74137	Logic	Add. Register a. invert. Outputs	20-MP		—
74136	CMOS-Logic	Qued 2-Input OR Driver (30V)	t6-DIP		—
74t36	CMOS-Logic		20-MP		—
74t38/1	TTL-Logic	3-Bit Binary Decoder/Demultiplexer,	t6-DIP		—
74t38/t	TTL-Logic	inverting	20-MP		—
74t38/2	TTL-Logic	Quad 2-Inpu1 OR Driver (30V)	14-DIP		—
74139	CMOS/TTL	Dual 2-Bit Binery	16-DIP		—
74139	Logic	Decoder/Demultiplexer, inverting	20-MP		—
7414	CMOS/TTL	Hex Schmitt Trigger Inverter	14-DIP		—
7414	Logic		20-MP		—
74140	TTL-Logic	Dual 4-Input 50-Ohm-NAND Power-Driver	t4-DIP		—
74140	TTL-Logic		20-MP		—
7414t	TTL-Logic	BCD-to-Decimal Decoder/Display Dnver	16-DIP		—
7414t	TTL-Logic	(60V)			—
74142	TTL-Logic	Synchronous Decimal Up Counter with	16-DIP		—
74142	TTL-Logic	Decimal-Dec. and Disp.-Dnver (60V)			—
74143	TTL-Logic	Decimal Up Counter with Output	24-DIP		—
74143	TTL-Logic	Register and 7-Segment-Decoder (15mA)			—
74t44	TTL-Logic	Decimal Up Counter with Output	24-DIP		—
74t44	TTL-Logic	Register and 7-Segment-Dec. (t5			—
74144	TTL-Logic	V/25mA)			—
74145	CMOS/TTL	BCD-to-Decimal Decoder/Display Driver	t6-DIP		—
74145	Logic	(15V)			—
74147	CMOS/TTL	Binary Decimal-to-BCD Priority Encoder	16-DIP		—
74147	Logic		20-MP		—
74148	CMOS/TTL	3-Bit Binary Priority Encoder	16-DIP		—
74148	Logic		20-MP		—
74149	CMOS-Logic	3-Bit Binary Priority Encoder	20-DIP		—
7415	TTL-Logic	Triple 3-Input AND Gate	14-DIP		—
74t5	TTL-Logic		20-MP		—
74t50	CMOS/TTL	t6-to-1 Deta Selector/Multiplexer	24-DIP		—
74t50	Logic	with inverting Output			—
74t51	CMOS/TTL	8-to-1 Deta Selector/Multiplexer with	16-DIP		—
74t51	Logic	Strobe	20-MP		—
74t52	CMOS/TTL	6-to-1 Data Selector/Multiplexer with	t4-DIP		—
74t52	Logic	inverting Output	20-MP		—
74153	CMOS/TTL	Dual 4-to-t Deta Selector/Multiplexer	16-DIP		—
74t53	Logic		20-MP		—
74t54	CMOS/TTL	4-Bit Binary Decoder/Demultiplexer	24-DIP		—
74t54	Logic	(50µA)	28-MP		—
74155	CMOS/TTL	Dual 2-Bit Binary	16-DIP		—
74155	Logic	Decoder/Demultiplexer	20-MP		—
74t56	CMOS/TTL	Dual 2-Bit Binary	t6-DIP		—
74t56	Logic	Decoder/Demultiplexer			—
74t57	CMOS/TTL	Quad 2-to-1 Deta Selector/Multiplexer	16-DIP		—
74157	Logic		20-MP		—
74158	CMOS/TTL	Quad 2-to-1 Data Selector/Multiplexer	t6-DIP		—
74156	Logic	with inverting Outputs	20-MP		—
74159	TTL-Logic	4-Bit Binary Decoder/Demultiplexer	24-DIP		—
74159	TTL-Logic	(50µA)			—

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7416	TTL-Logic	Hex Driver, inverting (15V)	14-DIP		—
74160	CMOS/TTL	Synchronous Decimal Up/Down Counter	16-DIP		—
74160	Logic	with Preset and Clear	20-MP		—
741604	TTL-Logic	Octal 2-to-1 Bus Multiplexer with	28-DIP		—
741604	TTL-Logic	Latch			—
74161	CMOS/TTL	Synchronous Binary 4-Bit Up Counter	16-DIP		—
74161	Logic	with Preset and Clear	20-MP		—
74162	CMOS/TTL	Synchronous Decimal Up/Down Counter	16-DIP		—
74162	Logic	with Preset and Clear	20-MP		—
741620	TTL-Logic	8-Bit Bi-Directional Bus Transceiver	20-DIP		—
741620	TTL-Logic	with Register, inverting	20-MP		—
741621	TTL-Logic	8-Bit Bi-Directional Bus Transceiver	20-DIP		—
741621	TTL-Logic	with Register, non inverting	20-MP		—
741622	TTL-Logic	6-Bit Bi-Directional Bus Transceiver	20-DIP		—
741622	TTL-Logic	with Register, inverting	20-MP		—
741623	TTL-Logic	8-Bit Bi-Directional Bus Transceiver	20-DIP		—
741623	TTL-Logic	with Register, non inverting	20-MP		—
74163	CMOS/TTL	Synchronous Binary 4-Bit Up Counter	16-DIP		—
74163	Logic	with Preset and Clear	20-MP		—
741631	TTL-Logic	Ouad Line Driver with Complementary	16-DIP		—
741631	TTL-Logic	Outputs (Line RS-422)	20-MP		—
741638	TTL-Logic	6-Bit Bi-Directional Bus Transceiver,	20-DIP		—
741638	TTL-Logic	inverting	20-MP		—
741639	TTL-Logic	8-Bit Bi-Directional Bus Transceiver,	20-DIP		—
741639	TTL-Logic	non inverting	20-MP		—
74164	CMOS/TTL	8-Bit Shift Register with parallel	14-DIP		—
74164	Logic	Outputs and Clear	20-MP		—
741640	TTL-Logic	6-Bit Bi-Directional Bus Transceiver,	20-DIP		—
741640	TTL-Logic	inverting	20-MP		—
741641	TTL-Logic	8-Bit Bi-Directional Bus Transceiver,	20-DIP		—
741641	TTL-Logic	non inverting	20-MP		—
741642	TTL-Logic	8-Bit Bi-Directional Bus Transceiver,	20-DIP		—
741642	TTL-Logic	inverting	20-MP		—
741643	TTL-Logic	6-Bit Bi-Directional Bus Transceiver,	20-DIP		—
741643	TTL-Logic	inverting/non inverting	20-MP		—
741644	TTL-Logic	8-Bit Bi-Directional Bus Transceiver,	20-DIP		—
741644	TTL-Logic	inverting/non inverting	20-MP		—
741645	TTL-Logic	6-Bit Bi-Directional Bus Transceiver,	20-DIP		—
741645	TTL-Logic	non inverting	20-MP		—
74165	CMOS/TTL	8-Bit Shift Register with parallel	16-DIP		—
74165	Logic	Inputs and Clear	20-MP		—
74166	CMOS/TTL	8-Bit Shift Register with parallel	16-DIP		—
74166	Logic	Inputs and Clear	20-MP		—
74167	TTL-Logic	Synchronous Programmable Decimal	16-DIP		—
74167	TTL-Logic	Frequency Divider			—
74166	CMOS/TTL	Synchronous Decimal Up/Down Counter	16-DIP		—
74166	Logic	with Preset			—
74169	CMOS/TTL	Synchronous Binary 4-Bit Up/Down	16-DIP		—
74169	Logic	Counter with Preset	20-MP		—
7417	TTL-Logic	Hex Driver, non inverting	14-DIP		—
74170	TTL-Logic	4x4-Bit Random Access Memory (RAM)	16-DIP		—
74170	TTL-Logic		20-MP		—
74171	TTL-Logic	Ouad D-Flip-Flop with Complementary	16-DIP		—
74171	TTL-Logic	Outputs and Clear	20-MP		—
74172	TTL-Logic	8x2-Bit RAM	24-DIP		—
74173	CMOS/TTL	4-Bit D-Register with Enable and	16-DIP		—
74173	Logic	Clear, non inverting	20-MP		—
74174	CMOS/TTL	6-Bit D-Register with Clear, non	16-DIP		—
74174	Logic	inverting	20-MP		—
74175	CMOS/TTL	4-Bit D-Register with Clear, non	16-DIP		—
74175	Logic	inverting	20-MP		—
74176	TTL-Logic	Asynchronous Decimal Up Counter with	14-DIP		—
74176	TTL-Logic	Preset and Clear			—
741761	TTL-Logic	DRAM and Interrupt-Vektor Controller	48-DIP		—
741761	TTL-Logic		44-MP		—
741762	TTL-Logic	Memory Address Multiplexer for 4 MBit	40-DIP		—

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741762	TTL-Logic	Dynamic RAMs	44-MP		—
741763	TTL-Logic	Intelligence Controller for Dynamic	48-DIP		—
741763	TTL-Logic	RAMs(IDC)	44-MP		—
741764	TTL-Logic	Dual Port Controllar 1 MBit Dynamic	48-DIP		—
741764	TTL-Logic	RAMs	44-MP		—
741765	TTL-Logic	Dual Port Controller 1 MBit Dynamic	48-DIP		—
741765	TTL-Logic	RAMs	44-MP		—
74177	TTL-Logic	Asynchronous Binary 4-Bit Up Counter	14-DIP		—
74177	TTL-Logic	with Preset and Clear			—
741779	TTL-Logic	Binary 8-Bit Up/Down Counter	16-DIP		—
74176	TTL-Logic	4-Bit Shift Register with parallel	14-DIP		—
74176	TTL-Logic	Inputs/Outputs and Clear			—
74179	TTL-Logic	4-Bit Shift Register with parallel	16-DIP		—
74179	TTL-Logic	Inputs/Outputs and Clear			—
7418	TTL-Logic	Dual 4-Input NAND Schmitt Trigger	14-DIP		—
7416	TTL-Logic		20-MP		—
74180	CMOS/TTL	9-Bit Parity Generator/Parity Checker	14-DIP		—
74160	Logic		20-MP		—
741601	TTL-Logic	Serial Encoder/Decoder/Data Selector	24-DIP		—
741601	TTL-Logic	for Disk Drives			—
741802	TTL-Logic	Serializer/Deserializer for Data	46-DIP		—
741802	TTL-Logic	Communication	68-MP		—
741803	TTL-Logic	Quad D-Flip-Flop with Clockdriver and	14-DIP		—
741803	TTL-Logic	Outputdriver, non inverting			—
741804	TTL-Logic	Hex 2-Input NAND Driver	20-DIP		—
741805	TTL-Logic	Hex 2-Input NOR Driver	20-DIP		—
741608	TTL-Logic	Hex 2-Input AND Driver	20-DIP		—
74181	CMOS/TTL	4-Bit Arithmetic/Logic Unit, Function	24-DIP		—
74181	Logic	Generator			—
741811	TTL-Logic	Serial Encoder/Decoder/Data Selector	24-DIP		—
741811	TTL-Logic	for Disk Drives			—
741812	TTL-Logic	Serializer/Deserializer for Data	48-DIP		—
741812	TTL-Logic	Communication	68-MP		—
74182	CMOS/TTL	Carry Unit for 74180, 74168, 74181,	16-DIP		—
74182	Logic	74281, 74381	20-MP		—
741821	TTL-Logic	10-Bit D-Register, non inverting	24-DIP		—
741823	TTL-Logic	9-Bit D-Register with Clockenable and	24-DIP		—
741823	TTL-Logic	Clear, non inverting			—
74183	cmos/ttl	Dual 1-Bit Full Adder	14-DIP		—
741832	TTL-Logic	Hex 2-Input OR Driver	20-DIP		—
74184	TTL-Logic	5-Bit Cascedable BCD-to-Binary Code	18-DIP		—
74184	TTL-Logic	Transposer			—
74185	TTL-Logic	6-Bit Binary-to-BCD Code Transposer	16-DIP		—
74186	TTL-Logic	64x8-Bit Programmable Read Only Memory	24-DIP		—
74187	TTL-Logic	256x4-Bit Read Only Memory (ROM)	16-DIP		—
74186	TTL-Logic	32x8-Bit Programmable Read Only	16-DIP		—
74188	TTL-Logic	Memory (PROM)			—
74189	CMOS/TTL	16x4-Bit RAM	16-DIP		—
74189	Logic				—
741894	TTL-Logic	9-Bit Bus Transceiver with Parity	28-DIP		—
741894	TTL-Logic	Generator and Latch, non inverting			—
741895	TTL-Logic	9-Bit Bus Transceiver with Parity	28-DIP		—
741895	TTL-Logic	Generator and Latch, non inverting			—
741896	TTL-Logic	9-Bit Bus Transceiver with Parity	28-DIP		—
741896	TTL-Logic	Generator and Register, non inverting			—
741897	TTL-Logic	9-Bit Bus Transceiver with Parity	28-DIP		—
741897	TTL-Logic	Generator and Register, non inverting	44-MP		—
7419	TTL-Logic	Hex Schmitt Trigger Inverter	14-DIP		—
7419	TTL-Logic		20-MP		—
74180	CMOS/TTL	Synchronous Decimal Up/Down Counter	18-DIP		—
74190	Logic	with Preset	20-MP		—
74191	CMOS/TTL	Synchronous Binary 4-Bit Up/Down	16-DIP		—
74191	Logic	Counter with Preset	20-MP		—
74192	CMOS/TTL	Synchronous Decimal Up/Down Counter	16-DIP		—
74192	Logic	with Preset	20-MP		—
74193	CMOS/TTL	Synchronous Binary 4-Bit Up/Down	18-DIP		—

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74193	Logic	Counter with Preset	20-MP		—
74194	CMOS/TTL	4-Bit Shift Register with parallel	16-DIP		—
74194	Logic	Input/Output, right/left with Clear	20-MP		—
74195	CMOS/TTL	4-Bit Shift Register with parallel	16-DIP		—
74195	Logic	Input/Output, right/left with Clear	20-MP		—
74196	TTL-Logic	Asynchronous Decimal Up Counter with	14-DIP		—
74196	TTL-Logic	Preset and Clear	20-MP		—
74197	TTL-Logic	Asynchronous Binary 4-Bit Up Counter	14-DIP		—
74197	TTL-Logic	with Preset and Clear	20-MP		—
74196	TTL-Logic	6-Bit Shift Register with parallel	24-DIP		—
74196	TTL-Logic	Input/Output, right/left shifting			—
74199	TTL-Logic	8-Bit Shift Register with parallel	24-DIP		—
74199	TTL-Logic	Inputs/Outputs and Clear			—
7420	CMOS/TTL	Dual 4-Input NAND Gate	14-DIP		—
7420	Logic		20-MP		—
7420/2	TTL-Logic	Dual 4-Input NAND Gate	14-DIP		—
74200	CMOS/TTL	256x1-Bit RAM	16-DIP		—
74200	Logic				—
742000	TTL-Logic	16-Bit Direction Discriminator	28-DIP		—
74201	TTL-Logic	256x1-Bit RAM	16-DIP		—
74202	TTL-Logic	256x1-Bit RAM	16-DIP		—
74206	TTL-Logic	256x1-Bit RAM	16-DIP		—
74207	TTL-Logic	256x4-Bit RAM	16-DIP		—
74206	TTL-Logic	256x4-Bit RAM	20-DIP		—
7421	CMOS/TTL	Dual 4-Input AND Gate	14-DIP		—
7421	Logic		20-MP		—
7421/2	TTL-Logic	Dual 4-Input AND Gate	14-DIP		—
74214	TTL-Logic	1024x1-Bit RAM	16-DIP		—
74215	TTL-Logic	1024x1-Bit RAM	16-DIP		—
74219	TTL-Logic	16x4-Bit RAM	16-DIP		—
74219	TTL-Logic		20-MP		—
7422/1	TTL-Logic	Dual 4-Input NAND Gate	14-DIP		—
7422/1	TTL-Logic		20 MP		—
7422/2	TTL-Logic	Dual 4-Input NAND Gate	14-DIP		—
74221	CMOS/TTL	Dual Monoflop with Schmitt Trigger	16-DIP		—
74221	Logic	Input and Clear	20-MP		—
74222	TTL-Logic	16x4-Bit FIFO	24-DIP		—
742226	CMOS-Logic	64x1-and 256x1-Bit FIFO	24-DIP		—
742227	CMOS-Logic	64x-and 256x1 -Bit Clocked FIFO	28-DIP		—
742226	CMOS-Logic	64x1-and 256x1-Bit FIFO	24-DIP		—
742229	CMOS-Logic	64x1-and 256x1 -Bit Clocked FIFD	28-DIP		—
742232	TTL-Logic	64x8-Bit FIFO	24-DIP		—
742232	TTL-Logic		26-MP		—
742233	TTL-Logic	64x9-Bit FIFO	28-DIP		—
742233	TTL-Logic		26-MP		—
742235	CMOS-Logic	1024x9x2-Bit Bidirectional FIFOs	44-MP		—
742236	CMOS-Logic	1024x9x2-Bit Bidirectional FIFOs	44-MP		—
742236	TTL-Logic	32x9-Bit FIFO	40-DIP		—
742236	TTL-Logic		44-MP		—
742239	TTL-Logic	32x9-Bit FIFO	40-DIP		—
742239	TTL-Logic		44-MP		—
74224	TTL-Logic	16x4-Bit FIFO	20-DIP		—
74224	TTL-Logic		26-MP		—
742240	TTL-Logic	Octal Bus Line Driver for	20-DIP		—
742240	TTL-Logic	MOS-Element, inverting	20-MP		—
742241	TTL-Logic	Octal Bus Line Driver for	20-DIP		—
742241	TTL-Logic	MOS-Elements, non inverting	20-MP		—
742242	TTL-Logic	Quad Bus Transceiver for	14-DIP		—
742242	TTL-Logic	MOS-Elements, inverting	20-MP		—
742243	TTL-Logic	Qued Bus Transceiver, non inverting	14-DIP		—
742243	TTL-Logic		20-MP		—
742244	TTL-Logic	Octal Bus Line Driver for	20-DIP		—
742244	TTL-Logic	MOS-Elements, non inverting	20-MP		—
74225	TTL-Logic	16x5-Bit FIFO	20-DIP		—
74226	TTL-Logic	4-Bit Universal Bus Transceiver with	16-DIP		—
74226	TTL-Logic	Register, non inverting			—

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74227	TTL-Logic	16x4-Bit FIFO	20-DIP		—
74228	TTL-Logic	16x4-Bit FIFO	16-DIP		—
74229	TTL-Logic	16x5-Bit FIFO	20-DIP		—
74229	TTL-Logic		20-MP		—
7423	TTL-Logic	Dual 4-Input NOR Gate and Strobe, 1	16-DIP		—
7423	TTL-Logic	Gate expandable			—
74230	CMOS/TTL	Quad Line Driver, 4 inverting, 4 non	20-DIP		—
74230	Logic	Inverting, with Separet Enable			—
74231	CMOS/TTL	Octal 4-Bit Line Driver with Seperate	20-DIP		—
74231	Logic	Enable Inputs, inverting			—
74232	TTL-Logic	16x4-Bit FIFO	16-DIP		—
74232	TTL-Logic		20-MP		—
74233	TTL-Logic	16x5-Bit FIFO	20-DIP		—
74233	TTL-Logic		20-MP		—
74234	TTL-Logic	64x4-Bit FIFO	16-DIP		—
74234	TTL-Logic		20-MP		—
74235	TTL-Logic	64x5-Bit FIFO	20-DIP		—
74235	TTL-Logic		20-MP		—
74236	TTL-Logic	64x4-Bit FIFO	16-DIP		—
74236	TTL-Logic		20-MP		—
74237	CMOS-Logic	3-Bit Binary Decoder	16-DIP		—
74237	CMOS-Logic		20-MP		—
74238	CMOS-Logic	3-Bit Binary Decoder/Demultiplexerw.	16-DIP		—
74236	CMOS-Logic	Add. Latch a. noninvert. Outputs	20-MP		—
74239	CMOS-Logic	Dual 2-Bit Binary	16-DIP		—
74239	CMOS-Logic	Decoder/Demultiplexer	20-MP		—
7424	TTL-Logic	Quad 2-Input NAND Schmitt Trigger	14-DIP		—
7424	TTL-Logic		20-MP		—
74240	CMOS/TTL	Octal Bus Line Driver, inverting	20-DIP		—
74240	Logic		20-MP		—
74241	CMOS/TTL	Octal Bus Line Driver, noninverting	20-DIP		—
74241	Logic		20-MP		—
74242	CMOS/TTL	Quad Bi-Directional Bus Transceiver,	14-DIP		—
74242	Logic	inverting	20-MP		—
74243	CMOS/TTL	Quad Bus Transceiver, noninverting	14-DIP		—
74243	Logic		20-MP		—
74244	CMOS/TTL	Octal Bus Line Driver, noninverting	20-DIP		—
74244	Logic		20-MP		—
74245	CMOS/TTL	Quad Bus Transceiver, noninverting	20-DIP		—
74245	Logic		20-MP		—
74246	TTL-Logic	BCD-to-7-Segment Decoder/Display	16-DIP		—
74246	TTL-Logic	Driver (30V)			—
74247	TTL-Logic	BCD-to-7-Segment Decoder/Display	16-DIP		—
74247	TTL-Logic	Driver (15V)	20-MP		—
74248	TTL-Logic	BCD-to-7-Segment Decoder/Display	16-DIP		—
74248	TTL-Logic	Driver	20-MP		—
74249	TTL-Logic	BCD-to-7-Segment Decoder/Display	16-DIP		—
74249	TTL-Logic	Driver (5,5V)			—
7425	TTL-Logic	Dual 4-Input NOR Gate and Strobe	14-DIP		—
74250	TTL-Logic	16-to-1 Data Selector/Multiplexer	24-DIP		—
74250	TTL-Logic		26-MP		—
74251	CMOS/TTL	6-to-1 Data Selector/Multiplexer with	16-DIP		—
74251	Logic	Enable	20-MP		—
74253	CMOS/TTL	Dual 4-to-1 Data Selector/Multiplexer	16-DIP		—
74253	Logic		20-MP		—
742540	TTL-Logic	Octal Bus Line Driver for	20-DIP		—
742540	TTL-Logic	MOS-Element, inverting	20-MP		—
742541	TTL-Logic	Octal Bus Line Driver for	20-DIP		—
742541	TTL-Logic	MOS-Elements, noninverting	20-MP		—
74256	TTL-Logic	Dual 4-Bit Addressable D-Latch, non	16-DIP		—
74256	TTL-Logic	inverting	20-MP		—
74257	CMOS/TTL	Quad 2-to-1 Data Selector/Multiplexer	16-DIP		—
74257	Logic		20-MP		—
74256	CMOS/TTL	Quad 2-to-1 Data Selector/Multiplexer	16-DIP		—
74258	Logic	with inverting Outputs	20-MP		—
74259	CMOS/TTL	8-Bit Addressable Latch with Enable	16-DIP		—

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74259	Logic	and Clear	20-MP		—
7426	TTL-Logic	Quad 2-Input NAND Gate (15V)	14-DIP		—
7426	TTL-Logic		20-MP		—
74260	TTL-Logic	Dual 5-Input NOR Gate	14-DIP		—
74260	TTL-Logic		20-MP		—
74261	TTL-Logic	2x4-Bit Multiplier	16-DIP		—
74261	TTL-Logic		20-MP		—
742620	TTL-Logic	8-Bit Bus Transceiver for	20-DIP		—
742620	TTL-Logic	MOS-Elements with Register, non	20-MP		—
742820	TTL-Logic	inverting			—
742623	TTL-Logic	8-Bit Bus Transceiver for	20-DIP		—
742623	TTL-Logic	MOS-Elements with Register, non	20-MP		—
742623	TTL-Logic	inverting			—
74264	TTL-Logic	Carry Unit for Counters	16-DIP		—
74264	TTL-Logic		20-MP		—
742640	TTL-Logic	6-Bit Bus Transceiver for	20-DIP		—
742640	TTL-Logic	MOS-Elements, inverting	20-MP		—
742643	TTL-Logic	6-Bit Bi-Directional Bus Transceiver,	20-DIP		—
742643	TTL-Logic	inverting/non inverting			—
742645	TTL-Logic	8-Bit Bus Transceiver for	20-DIP		—
742645	TTL-Logic	MOS-Elements, non inverting	20-MP		—
74265	TTL-Logic	Dual NAND Gate and 2 Inverters with	16-DIP		—
74265	TTL-Logic	Complementery Outputs			—
74266	CMOS/TTL	Quad 2-input EX-NOR Gate	14-DIP		—
74266	Logic		20-MP		—
74266	TTL-Logic	Synchronous Binary 8-Bit Up/Down	24-DIP		—
74269	TTL-Logic	Counter with Prsset			—
7427	CMOS/TTL	Triple 3-Input NOR Gate	14-DIP		—
7427	Logic		20-MP		—
74270	TTL-Logic	512x4-Bit Read Only Memory ROM)	16-DIP		—
742708	CMOS-Logic	64x9-Bit FIFO	28-DIP		—
742708	CMOS-Logic		28-MP		—
74271	TTL-Logic	256x8-Bit Read Only Memory (ROM)	20-DIP		—
74273	CMOS/TTL	6-Bit D-Register with Clear, non	20-DIP		—
74273	Logic	inverting	20-MP		—
74274	TTL-Logic	4x4-Bit Multiplier	20-DIP		—
74275	TTL-Logic	7-Bit Wallecs Tree Element	16-DIP		—
74276	TTL-Logic	Quad Negativs Edge Triggered JK	20-DIP		—
74276	TTL-Logic	Flip-Flops with Common Preset and			—
74276	TTL-Logic	Clear			—
74278	TTL-Logic	Cascadable 4-Bit Priority Register	14-DIP		—
74279	CMOS/TTL	Ouad NAND RS Flip-Flops	16-DIP		—
74279	Logic		20-MP		—
7428	TTL-Logic	Quad 2-Input NOR Power-Gate (FQ=30)	14-DIP		—
7428	TTL-Logic		20-MP		—
74260	CMOS/TTL	9-Bit Parity Gansrator/Perity Checker	16-DIP		—
74260	Logic		20-MP		—
74281	TTL-Logic	4-Bit Accumulator	24-DIP		—
74282	TTL-Logic	Carry Unit with Selectable Carry	20-DIP		—
74282	TTL-Logic	Inputs	20-MP		—
74283	CMOS/TTL	4-Bit Full Adder	16-DIP		—
74283	Logic		20-MP		—
74264	TTL-Logic	4x4-Bit Multiplier	16-DIP		—
74285	TTL-Logic	4x4-Bit Multiplier	16-DIP		—
74286	TTL-Logic	9-Bit Parity Generator/Parity Checker	14-DIP		—
74266	TTL-Logic		20-MP		—
74267	TTL-Logic	256x4-Bit FROM	16-DIP		—
74266	TTL-Logic	32x8-Bit Programmabls Rsad Only	16-DIP		—
74288	TTL-Logic	Memory (PROM)			—
74289	TTL-Logic	16x4-Bit RAM	16-DIP		—
74290	TTL-Logic	Asynchronous Decimal Up Counter	14-DIP		—
74290	TTL-Logic		20-MP		—
74291	TTL-Logic	4-Bit Universal Shift Register and	20-DIP		—
74291	TTL-Logic	binary Counter			—
74292	CMOS/TTL	Programmabls 32-Bit Binary Frequency	16-DIP		—
74292	Logic	Divider	20-MP		—

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74293	CMOS/TTL	Asynchronous Binary 4-Bit Up Counter	16-DIP		—
74293	Logic				—
7429368	TTL-Logic	Controller for 1 MBit Dynamic RAMs	68-MP		—
74294	CMOS/TTL	Programmable 16-Bit Binary Frequency	16-DIP		—
74294	Logic	Divider	20-MP		—
74295	TTL-Logic	4-Bit Shift Register with parallel	14-DIP		—
74295	TTL-Logic	Inputs/Outputs and Clear	20-MP		—
742952	CMOS/TTL	8-Bit Bi-Directional Bus Transceiver	24-DIP		—
742952	Logic	with Register, non inverting			—
7429520	CMOS-Logic	6-Bit Positive Edge Triggered	24-DIP		—
7429520	CMOS-Logic	Pipeline Register			—
7429521	CMOS-Logic	6-Bit Positive Edge Triggered	24-DIP		—
742952t	CMOS-Logic	Pipeline Register			—
742953	CMOS/TTL	6-Bit Bus Transceiver with Register,	24-DIP		—
742953	Logic	inverting			—
742960	TTL-Logic	t6-Bit Parallel Error-Detecting and	48-DIP		—
742960	TTL-Logic	Correcting Element (EDAC)			—
742961	TTL-Logic	4-Bit Multible Bus Buffer for 742960,	24-DIP		—
742961	TTL-Logic	non inverting			—
742962	TTL-Logic	4-Bit Multible Bus Buffer for 742960,	24-DIP		—
742962	TTL-Logic	inverting			—
742968	TTL-Logic	Controller for 1 M Bit Dynamic RAMs	48-DIP		—
74297	CMOS/TTL	Digital Phase-Locked-Loop Element	16-DIP		—
74297	Logic	(PLL)			—
742970	TTL-Logic	Memory Timing Controller for 64/256	t4-DIP		—
742970	TTL-Logic	KBit Dynamic RAMe (MTI)	28-MP		—
74296	CMOS/TTL	Quad 2-to-1 Deta Selector/Multiplexer	t6-DIP		—
74296	Logic	with Register	20-MP		—
7429606	TTL-Logic	6-Bit Comparator and 2- to 4-Bit	24-DIP		—
7429606	TTL-Logic	decoder	26-MP		—
7429609	TTL-Logic	9-Bit Comparator	24-DIP		—
7429609	TTL-Logic		26-MP		—
7429616	TTL-Logic	6-Bit Diegnostic/Pipeline Reglsler	24-DIP		—
7429616	TTL-Logic		26-MP		—
7429821	TTL-Logic	10-Bit D-Register, non inverting	24-DIP		—
7429621	TTL-Logic		26-MP		—
7429622	TTL-Logic	10-Bit D-Register, inverting	24-DIP		—
7429822	TTL-Logic		28-MP		—
7429623	TTL-Logic	9-Bit D-Register with Clockenable and	24-DIP		—
7429823	TTL-Logic	Clear, non inverting	28-MP		—
7429824	TTL-Logic	9-Bit D-Register with Clockenable and	24-DIP		—
7429824	TTL-Logic	Clear, inverting	26-MP		—
7429625	TTL-Logic	8-Bit D-Register with Clockenable and	24-DIP		—
7429625	TTL-Logic	Clear, non inverting	28-MP		—
7429626	TTL-Logic	6-Bit D-Register with Clockenable and	24-DIP		—
7429626	TTL-Logic	Clear, inverting	28-MP		—
7429827	TTL-Logic	10-Bit Bus Driver, non inverting	24-DIP		—
7429827	TTL-Logic		28-MP		—
7429826	TTL-Logic	10-Bit Bus Driver, inverting	24-DIP		—
7429626	TTL-Logic		28-MP		—
7429833	TTL-Logic	8-Bit Bus Transceiver with Parity	24-DIP		—
7429833	TTL-Logic	Generator, non inverting	28-MP		—
7429634	TTL-Logic	8-Bit Bus Transceiver with Parity	24-DIP		—
7429634	TTL-Logic	Generator, inverting			—
7429841	TTL-Logic	t0-Bit D-Latch, non inverting	24-DIP		—
7429642	TTL-Logic	t0-Bit D-Latch with Enable, inverting	24-DIP		—
7429842	TTL-Logic		28-MP		—
7429843	TTL-Logic	9-Bit D-Latch with Preset and Clear,	24-DIP		—
7429643	TTL-Logic	non inverting			—
7429644	TTL-Logic	9-Bit D-Latch with Preset end Clear,	24-DIP		—
7429844	TTL-Logic	inverting			—
7429645	TTL-Logic	8-Bit D-Latch with 3-Enable-Inputs,	24-DIP		—
7429645	TTL-Logic	Preset and Clear, non inverting	28-MP		—
7429646	TTL-Logic	8-Bit D-Latch with 3-Enable-Inputs,	24-DIP		—
7429646	TTL-Logic	Preset and Clear, inverting	28-MP		—
7429653	TTL-Logic	6-Bit Bus Transceiver with Parity	24-DIP		—

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7429853	TTL-Logic	Generator, non inverting	28-MP		—
7429854	TTL-Logic	8-Bit Bus Transceiver with Parity	24-DIP		—
7429854	TTL-Logic	Generator, inverting	28-MP		—
7429861	TTL-Logic	10-Bit Bus Transceiver, non inverting	24-DIP		—
7429861	TTL-Logic		26-MP		—
7429862	TTL-Logic	10-Bit Bus Transceiver, inverting	24-DIP		—
7429862	TTL-Logic		28-MP		—
7429863	TTL-Logic	9-Bit Bus Transceiver, non inverting	24-DIP		—
7429863	TTL-Logic		28-MP		—
7429864	TTL-Logic	9-Bit Bus Transceiver, inverting	24-DIP		—
7429864	TTL-Logic		28-MP		—
74298	CMOS/TTL	8-Bit Shift Register with parallel	20-DIP		—
74299	Logic	Input/Output, right/left shifting	20-MP		—
7430	CMOS/TTL	8-Input NAND Gate	14-DIP		—
7430	Logic		20-MP		—
7430/2	TTL-Logic	8-Input NAND Gate	14-DIP		—
74300	TTL-Logic	256x1-Bit RAM	18-DIP		—
74301	TTL-Logic	256x1-Bit RAM	18-DIP		—
74302	TTL-Logic	256x1-Bit RAM	16-DIP		—
7430240	TTL-Logic	Octel Enable 30-Ohm-Power Driver,	24-DIP		—
7430240	TTL-Logic	inverting			—
7430244	TTL-Logic	Octal Enable 30-Ohm-Power Driver, non	24-DIP		—
7430244	TTL-Logic	inverting			—
7430245	TTL-Logic	Octal 30-Ohm-Transceiver, non	24-DIP		—
7430245	TTL-Logic	inverting			—
74303	TTL-Logic	Quad 2-to-1 Divider/Clock Driver	16-DIP		—
743037	TTL-Logic	Quad 2-Input 30-Ohm-NAND Line Driver	18-DIP		—
743038	TTL-Logic	Quad 2-Input 30-Ohm-NAND Line Driver	16-DIP		—
74304	TTL-Logic	Quad 2-to-1 Divider/Clock Driver	16-DIP		—
743040	TTL-Logic	Dual 4-Input 30-Ohm-NAND Line Driver	18-DIP		—
74305	TTL-Logic	Quad 2-to-1 Divider/Clock Driver	16-DIP		—
7430640	TTL-Logic	Octal 30-Ohm-Transceiver, inverting	24-DIP		—
743074	TTL-Logic	Dual Edge Triggered D-Flip-Flop, non	14-DIP		—
743074	TTL-Logic	inverting	20-MP		—
7431	TTL-Logic	Hex Delay Element	18-DIP		—
7431	TTL-Logic		20-MP		—
74314	TTL-Logic	1024x1-Bit RAM	16-DIP		—
74315	TTL-Logic	1024x1-Bit RAM	16-DIP		—
74319	TTL-Logic	1024x1-Bit RAM	16-DIP		—
7432	CMOS/TTL	Quad 2-Input OR Gate	14-DIP		—
7432	Logic		20-MP		—
74320	TTL-Logic	Crystel Oscillator with Complementary	16-DIP		—
74320	TTL-Logic	Outputs			—
74321	TTL-Logic	Crystal Oscillator with Complementary	18-DIP		—
74321	TTL-Logic	Outputs and Divider			—
74322	TTL-Logic	8-Bit Shift Register with parallel	20-DIP		—
74322	TTL-Logic	Input/Output and Sign Expander	20-MP		—
74323	CMOS/TTL	8-Bit Shift Register with parallel	20-DIP		—
74323	Logic	Input/Output, right/leftw. Memory	20-MP		—
74324	TTL-Logic	Voltage-Controlled Oscillator with	14-DIP		—
74324	TTL-Logic	Enable and Complementary Outputs			—
74325	TTL-Logic	Dual Voltage-Controlled Oscillator	16-DIP		—
74325	TTL-Logic	with Complementery Outputs			—
74326	TTL-Logic	Dual Voltage-Controlled Oscillator	18-DIP		—
74326	TTL-Logic	with Enable and Complementary Outputs			—
74327	TTL-Logic	Dual Voltage-Controlled Oscillator	14-DIP		—
7433	TTL-Logic	Quad 2-Input NOR Power-Gate	14-DIP		—
7433	TTL-Logic		20-MP		—
74330	TTL-Logic	12x50x6 Programmable Logic Array	20-DIP		—
74330	TTL-Logic	(FPLA)			—
74331	TTL-Logic	12x50x6 Programmable Logic Array	20-DIP		—
74331	TTL-Logic	(FPLA)			—
743374	TTL-Logic	8-Bit D-Register with Clockanable,	20-DIP		—
743374	TTL-Logic	non inverting			—
7434	CMOS/TTL	Hex Driver, non inverting	14-DIP		—
74340	TTL-Logic	Octal Bus Line Driver, inverting	20-DIP		—

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74341	TTL-Logic	Octal Bus Line Driver, non inverting	20-DIP		—
74344	TTL-Logic	Octal Bus Line Driver, non inverting	20-DIP		—
74347	TTL-Logic	BCD-to-7-Segment Decoder/Display	16-DIP		—
74347	TTL-Logic	Driver (7V)			—
74348	TTL-Logic	3-Bit Binary Priority Encoder	16-DIP		—
74348	TTL-Logic		20-MP		—
7435	TTL-Logic	Hex Driver, non inverting	14-DIP		—
7435	TTL-Logic		20-MP		—
74350	TTL-Logic	4-Bit Delay Unit	16-DIP		—
74350	TTL-Logic		20-MP		—
74351	TTL-Logic	Dual 6-to-1 Data Selector/Multiplexer	20-DIP		—
74351	TTL-Logic	with inverting Outputs			—
74352	CMOS/TTL	Dual 4-to-1 Data Selector/Multiplexer	16-DIP		—
74352	Logic	with inverting Outputs	20-MP		—
74353	CMOS/TTL	Oual 4-to-1 Data Selector/Multiplexer	16-DIP		—
74353	Logic	with inverting Outputs	20-MP		—
74354	CMOS/TTL	8-to-1 Data Selector with	20-DIP		—
74354	Logic	Input-Register	20-MP		—
74355	TTL-Logic	8-to-1 Data Selector with	20-DIP		—
74355	TTL-Logic	Input-Register	20-MP		—
74356	CMOS/TTL	8-to-1 Data Selector with	20-DIP		—
74358	Logic	Input-Registar	20-MP		—
74357	TTL-Logic	6-to-1 Data Selector with	20-DIP		—
74357	TTL-Logic	Input-Register			—
7436	CMOS/TTL	Quad 2-Input NOR Gate	14-DIP		—
7436	Logic		20-MP		—
74362	TTL-Logic	Clock Oscillator for TMS 9900	16-DIP		—
74363	TTL-Logic	6-Bit D-Latch with Enable, non	20-DIP		—
74363	TTL-Logic	inverting			—
74364	TTL-Logic	8-Bit D-Register with Clockenable,	20-DIP		—
74364	TTL-Logic	non inverting			—
74365	CMOS/TTL	Hex Bus Lina Driver with Common	16-DIP		—
74365	Logic	Enable, non inverting	20-MP		—
74366	CMOS/TTL	Hex 2-Enable-Input Driver, inverting	18-DIP		—
74366	Logic		20-MP		—
74367	CMOS/TTL	Hex Bus Line Driver with Separate	16-DIP		—
74367	Logic	Enable Inputs 1. 4-a 2-Bit, non inv.	20-MP		—
74366	CMOS/TTL	Hex Bus Line Driver with Seperate	16-DIP		—
74366	Logic	Enable for 2- and 4-Bit, inverting	20-MP		—
7437	TTL-Logic	Quad 2-Input NAND Power-Gale (FQ=30)	14-DIP		—
7437	TTL-Logic		20-MP		—
74370	TTL-Logic	512x4-Bit Read Only Memory ROM)	18-DIP		—
74371	TTL-Logic	256x8-Bit Read Only Memory (ROM)	20-DIP		—
74373	CMOS/TTL	8-Bit D-Latch with Enable, non	20-DIP		—
74373	Logic	inverting	20-MP		—
74374	CMOS/TTL	8-Bit D-Register with Enable, non	20-DIP		—
74374	Logic	Inverting	20-MP		—
74375	CMOS/TTL	Dual 2-Bit D-Latch with Complementary	16-DIP		—
74375	Logic	Outputs	20-MP		—
74378	TTL-Logic	Quad Positive Edge Triggered JK	16-DIP		—
74376	TTL-Logic	Flip-Flop with Common Clock and Clear			—
74377	CMOS/TTL	8-Bit D-Register with Clockenable,	20-DIP		—
74377	Logic	non inverting	20-MP		—
74378	CMOS/TTL	6-Bit D-Register with Clock Enable,	20-DIP		—
74378	Logic	non inverting	20-MP		—
74379	CMOS/TTL	Quad D-Flip-Flop with Complementary	16-DIP		—
74379	Logic	Outputs and Clear	20-MP		—
7436	TTL-Logic	Quad 2-Input NAND Power-Gate (FQ=30)	14-DIP		—
7436	TTL-Logic		20-MP		—
74380	TTL-Logic	8-Bit Multifunction Register with	24-DIP		—
74380	TTL-Logic	Clockenable and Complementary Outputs	28-MP		—
7436I	CMOS/TTL	4-Bit Anthmetic/Logic Unit, Function	20-DIP		—
74381	Logic	Generator			—
74382	TTL-Logic	4-Bit Anthmetic/Logic Unit, Function	20-DIP		—
74382	TTL-Logic	Generator	20 MP		—
74364	CMOS/TTL	8xl-Bit Multiplier	16-DIP		—

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74384	Logic				—
74385	TTL-Logic	Quad Serial Adder/Subtracteurs with	20-DIP		—
74385	TTL-Logic	Internal Carry	20-MP		—
74386	CMOS/TTL	Quad 2-Input EX-OR Gate	14-DIP		—
74386	Logic		20-MP		—
74387	TTL-Logic	256x4-Bit PROM	16-DIP		—
743893	TTL-Logic	Quad Transceiver (IEEE 896-Standard)	20-MP		—
7439	TTL-Logic	Quad 2-Input NAND Power-Gate (FQ=30)	14-DIP		—
74390	CMOS/TTL	Dual Asynchronous Decimal Up Counter	16-DIP		—
74390	Logic	with Seperate Dividar 2:1 and 5:1	20-MP		—
74393	CMOS/TTL	Dual Asynchronous Binary 4-Bit Up	14-DIP		—
74393	Logic	Counter	20-MP		—
74395	TTL-Logic	4-Bit Shift Register with parallel	16-DIP		—
74395	TTL-Logic	Inputs/Outputs and Clear	20-MP		—
74396	TTL-Logic	8-Bit D-Register with 2x4-Bit Serial	16-DIP		—
74396	TTL-Logic	Input and Parallel Output	20-MP		—
74396	CMOS/TTL	Quad 2-to-1 Data Selector/Multiplexer	20-DIP		—
74396	Logic	with Register			—
74399	CMOS/TTL	Quad 2-to-1 Data Selector/Multiplexer	16-DIP		—
74399	Logic	with Register	20-MP		—
7440/1	TTL-Logic	Dual 4-Input NAND Power Gate (FQ=30)	14-DIP		—
7440/1	TTL-Logic		20-MP		—
7440/2	TTL-Logic	Oual 4-Input NAND Power Gate (FQ=30)	14-DIP		—
74400	TTL-Logic	4096x1-Bit RAM	16-DIP		—
744002	CMOS-Logic	Dual 4-Input NOR Gate	14-DIP		—
744002	CMOS-Logic		20-MP		—
74401/1	TTL-Logic	4096x1-Bit RAM	18-DIP		—
74401/2	TTL-Logic	CRC Ganerator/CRC Checker	14-DIP		—
74401/2	TTL-Logic		20-MP		—
7440102	CMOS-Logic	Synchronous 2-Decada Down Counter	16-DIP		—
7440102	CMOS-Logic	with Praset	20-MP		—
7440103	CMOS-Logic	Asynchronous 6-Bit Down Counter with	16-DIP		—
74401	CMOS-Logic	Praset	20-MP		—
7440104	CMOS-Logic	4-Bit Shift Register with perallel	16-DIP		—
7440104	CMOS-Logic	Input/Output, right/left shifting			—
7440105	CMOS-Logic	16x4-Bit FIFO	16-DIP		—
744015	CMOS-Logic	Dual 4-Bit Shift Register with	14-DIP		—
744015	CMOS-Logic	perallel Outputs			—
744016	CMOS-Logic	Quad Bilateral Digital or Analog	14-DIP		—
744016	CMOS-Logic	Switch (4x1 Closer)			—
744017	CMOS-Logic	Synchronous Decimal Up Counter with	16-DIP		—
744017	CMOS-Logic	Decimal-Decoder	20-MP		—
74402	TTL-Logic	CRC Ganerator/CRC Checker	16-DIP		—
74402	TTL-Logic		20-MP		—
744020	CMOS-Logic	Asynchronous Binary 14-Bit Up Counter	16-DIP		—
744020	CMOS-Logic		20-MP		—
744022	CMOS-Logic	Synchronous Octal Counter decoded	16-DIP		—
744022	CMOS-Logic	Outputs	20-MP		—
744024	CMOS-Logic	Asynchronous Binary 7-Bit Up Counter	14-DIP		—
744024	CMOS-Logic		20-MP		—
744028	CMOS-Logic	BCD-to-Decimal Decoder	16-DIP		—
744028	CMOS-Logic		20-MP		—
74403	TTL-Logic	4x1-Bit FIFO	24-DIP		—
74403	TTL-Logic		28-MP		—
744040	CMOS-Logic	Asynchronous Binary 12-Bit Up Counter	18-DIP		—
744040	CMOS-Logic		20-MP		—
744046	CMOS-Logic	Phase-Locked-Loop Switcher (PLL)	16-DIP		—
744049	CMOS-Logic	Hex Inverter/Buffer	16-DIP		—
744049	CMOS-Logic		20-MP		—
744050	CMOS-Logic	Hex Buffer/TTL Driver, non inverting	16-DIP		—
744050	CMOS-Logic		20-MP		—
744051	CMOS-Logic	6-Channel Multiplexer, Analog/Digital	16-DIP		—
744052	CMOS-Logic	Oual 4-Channel Multiplexer,	16-DIP		—
744052	CMOS-Logic	Analog/Digital			—
744053	CMOS-Logic	Triple 2-Channel Multiplexer,	16-DIP		—
744053	CMOS-Logic	Analog/Digital			—

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744059	CMOS-Logic	16-Bit Programmable Divider	24-DIP		—
744060	CMOS-Logic	Asynchronous Binary 14-Bit Up Counter	16-DIP		—
744060	CMOS-Logic	with Internal Oscillator	20-MP		—
744061	CMOS-Logic	Asynchronous Binary 14-Bit Up Counter	16-DIP		—
744061	CMOS-Logic	with Internal Oscillator	20-MP		—
744066	CMOS-Logic	Quad Bilateral Digital or Analog	14-DIP		—
744066	CMOS-Logic	Switch (4x1 Closer)	20-MP		—
744067	CMOS-Logic	16-Channel Multiplexer/Demultiplexer,	24-DIP		—
744067	CMOS-Logic	analog/digital			—
74407	TTL-Logic	4-Bit Expandable Data Access Register	24-DIP		—
74407	TTL-Logic	(DAR)	28-MP		—
744072	CMOS-Logic	Dual 4-Input OR Gate	14-DIP		—
744072	CMOS-Logic		20-MP		—
744075	CMOS-Logic	Triple 3-Input OR Gate	14-DIP		—
744075	CMOS-Logic		20-MP		—
744078	CMOS-Logic	6-Input NOR/OR Gate	14-DIP		—
744078	CMOS-Logic		20-MP		—
744094	CMOS-Logic	6-Bit Shift Register with Output Latch	16-DIP		—
744094	CMOS-Logic		20-MP		—
7441	TTL-Logic	BCD-to-Dacimal Decoder/Display Driver	16-DIP		—
7441	TTL-Logic	(70V)			—
74410	TTL-Logic	16x4-Bit RAM	18-DIP		—
74412	TTL-Logic	8-Bit Multifunction-Latch with	24-DIP		—
74412	TTL-Logic	Status-Flip-Flop, non inverting			—
74413	TTL-Logic	64x4-Bit FIFO	16-DIP		—
7442	CMOS/TTL	BCD-to-Dacimal Dacoder	16-DIP		—
7442	Logic		20-MP		—
74420	TTL-Logic	32-Bit Error-Datecting and Correcting	48-DIP		—
74420	TTL-Logic	Element (EDAC)	52-MP		—
74422	TTL-Logic	Post-Triggerable Monoflop with Clear	14-DIP		—
74422	TTL-Logic		20-MP		—
74423	CMOS/TTL	Dual Post-Triggerable Monoflop with	16-DIP		—
74423	Logic	Clear	20-MP		—
74424	TTL-Logic	Clock Generator for INTEL 8080	16-DIP		—
74425	TTL-Logic	Quad Bus Line Driver, non inverting	14-DIP		—
74426	TTL-Logic	Quad Bus Line Driver, non inverting	14-DIP		—
74426	TTL-Logic	Systern Controlling Element for INTEL	40-DIP		—
74428	TTL-Logic	8060			—
7443	TTL-Logic	Excess-3-to-Decimal Decoder	16-DIP		—
744316	CMOS-Logic	Quad Digital or Analog Switch with	16-DIP		—
744316	CMOS-Logic	Lavel Translation			—
74432	TTL-Logic	8-Bit Multifunction-Latch with	24-DIP		—
74432	TTL-Logic	Status-Flip-Flop, inverting			—
74433	TTL-Logic	64x4-Bit FIFO	24-DIP		—
744351	CMOS-Logic	6-Chennel Multiplexer, Analog/Digital	20-DIP		—
744351	CMOS-Logic	with Latch			—
744352	CMOS-Logic	Dual 4-Channel Multiplexer,	20-DIP		—
744352	CMOS-Logic	Anelog/Digital with Latch			—
744353	CMOS-Logic	Triple 2-Channel Multiplexer,	20-DIP		—
744353	CMOS-Logic	Analog/Digital with Latch			—
74436	TTL-Logic	Hex Driver for Memory with 2 Enable	16-DIP		—
74436	TTL-Logic	Inputs, inverting			—
74437	TTL-Logic	Hex Driver with 2 Enable Inputs and	16-DIP		—
74437	TTL-Logic	Damp-Resistor, inverting			—
744374	TTL-Logic	Octal Edge Triggered Double	20-DIP		—
744374	TTL-Logic	D-Flip-Flop, non inverting			—
74436	TTL-Logic	Systern Controlling Element for INTEL	40-DIP		—
74436	TTL-Logic	8080			—
7444	TTL-Logic	Excess-3-Gray-to-Decimal Decoder	16-DIP		—
74440	TTL-Logic	Quad Tri-Directional Bus Transceiver,	20-DIP		—
74440	TTL-Logic	non inverting	20-MP		—
74441	TTL-Logic	Qued Tri-Directional Bus Transceiver,	20-DIP		—
74441	TTL-Logic	inverting	20-MP		—
74442	CMOS/TTL	Qued Tri-Directional Bus Transceiver,	20-DIP		—
74442	Logic	non inverting			—
74443	CMOS/TTL	Quad Tri-Directional Bus Transceiver,	20-DIP		—

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74443	Logic	inverting			—
74444	CMOS/TTL	4-Bit Tri-Directional Bus	20-DIP		—
74444	Logic	Transceiver, inverting/non inverting			—
74445	TTL-Logic	BCD-to-Decimal Decoder/Display Driver	16-DIP		—
74445	TTL-Logic	(7V)	20-MP		—
74446	TTL-Logic	Quad Bi-Directional Bus Transceiver	16-DIP		—
74446	TTL-Logic	w. indiv. Control. Inputs, inverting	20-MP		—
74447	TTL-Logic	BCD-to-7-Segment Decoder/Display	16-DIP		—
74447	TTL-Logic	Driver (7V)			—
74448	TTL-Logic	4-Bit Tri-Directional Bus	20-DIP		—
74446	TTL-Logic	Transceiver, inverting/non inverting			—
74449	TTL-Logic	Quad Bus Transceiver with Individual	16-DIP		—
74449	TTL-Logic	Controling Inputs, non inverting	20-MP		—
7445	TTL-Logic	BCD-to-Decimal Decoder/Display Driver	16-DIP		—
7445	TTL-Logic	(30V)			—
74450	TTL-Logic	16-to-1 Deta Selector/Multiplexer	24-DIP		—
74450	TTL-Logic	with Complementary Outputs	28-MP		—
74451	TTL-Logic	Dual 8-to-1 Deta Selector/Multiplexar	24-DIP		—
74451	TTL-Logic		28-MP		—
744510	CMOS-Logic	Synchronous Decimel Up/Down Counter	16-DIP		—
744510	CMOS-Logic	with Preset			—
744511	CMOS-Logic	BCD-to-7-Segment Decoder/Memory/Driver	16-DIP		—
744511	CMOS-Logic		20-MP		—
744514	CMOS-Logic	4-Bit Binary Decoder/Demultiplexer	24-DIP		—
744514	CMOS-Logic	with Input Latch	28-MP		—
744515	CMOS-Logic	4-Bit Binary Decoder/Demultiplexer	24-DIP		—
744515	CMOS-Logic	with Input Latch	28-MP		—
744516	CMOS-Logic	Synchronous Decimal Up/Down Counter	18-DIP		—
744516	CMOS-Logic	with Preset			—
744518	CMOS-Logic	Dual Synchronous Decimal Up Counter	18-DIP		—
744518	CMOS-Logic		20-MP		—
744520	CMOS-Logic	Dual Synchronous Binary Up Counter	16-DIP		—
744520	CMOS-Logic		20-MP		—
74453	TTL-Logic	Quad 4-to-1 Deta Selector/Multiplexer	24-DIP	'	—
74453	TTL-Logic		28-MP		—
744538	CMOS-Logic	Dual Post-Triggeratile Pecision	16-DIP		—
744538	CMOS-Logic	Monoflop	20-MP		—
744543	CMOS-Logic	BCD-to-7-Segment Decoder/Memory/Driver	16-DIP		—
744543	CMOS-Logic		20-MP		—
74455	TTL-Logic	Octal Bus Driver with Parity	24-DIP		—
74455	TTL-Logic	Generator/Checker, inverting			—
74456	TTL-Logic	8-Bit Bus Driver with Parity	24-DIP		—
74456	TTL-Logic	Generator/Parity Checker, non			—
74456	TTL-Logic	inverting			—
7446	TTL-Logic	BCD-to-7-Segment Decoder/Display	16-DIP		—
7446	TTL-Logic	Driver (30V)			—
74460	TTL-Logic	10-Bit Comparator	24-DIP		—
74460	TTL-Logic		28-MP		—
74461	TTL-Logic	Synchronous Binery 8-Bit Up Counter	24-DIP		—
74461	TTL-Logic	with Preset, Clear and Register	28-MP		—
74465	TTL-Logic	Octal Buffer with Common Enable, non	20-DIP		—
74465	TTL-Logic	inverting	20-MP		—
74466	TTL-Logic	Octal Buffer with Common Enable,	20-DIP		—
74466	TTL-Logic	inverting	20-MP		—
74467	TTL-Logic	Dual 4-Bit Buffer with Separate	20-DIP		—
74467	TTL-Logic	Enable Inputs, non inverting	20-MP		—
74466	TTL-Logic	Octal 4-Bit Line Driver with Separate	20-DIP		—
74466	TTL-Logic	Enatile Inputs, inverting	20-MP		—
74469	TTL-Logic	Synchronous Binary 6-Bit Up/Down	24-DIP		—
74469	TTL-Logic	Counter with Preset and Register	28-MP		—
7447	TTL-Logic	BCD-to-7-Segment Decoder/Display	16-DIP		—
7447	TTL-Logic	Driver (15V)	20-MP		—
74470	TTL-Logic	256x8-Bit PROM	20-DIP		—
74471	TTL-Logic	256x6-Bit PROM	20-DIP		—
74472	TTL-Logic	512x6-Bit PROM	20-DIP		—
744724	CMOS-Logic	8-Bit Addressable D-Latch	16-DIP		—

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744724	CMOS-Logic		20-MP		—
74473	TTL-Logic	512x8-BitPROM	20-DIP		—
74474	TTL-Logic	512x8-BitPROM	24-DIP		—
74475	TTL-Logic	512x8-BitPROM	24-DIP		—
7448	CMOS/TTL	BCD-to-7-Segment Decoder/Display	18-DIP		—
7448	Logic	Driver			—
74481	TTL-Logic	4-Bit Slice Processor	48-DIP		—
74482	TTL-Logic	4-Bit Slice Microcontroller	20-DIP		—
74484	TTL-Logic	8-Bit Cascadable BCD-to-Binary Code	20-DIP		—
74484	TTL-Logic	Transposer			—
74485	TTL-Logic	9-Bit Binary-to-BCD Coda Transposer	20-DIP		—
74488	CMOS-Logic	IEEE-488 Bus Interface	48-DIP		—
7449	TTL-Logic	BCD-to-7-Segment Decoder/Display	14-DIP		—
7449	TTL-Logic	Driver (5,5V)	20-MP		—
74490	CMOS/TTL	Dual Asynchronous Decimal Up Counter	16-DIP		—
74490	Logic	with Seperate Divider 2:1 and 5:1	20-MP		—
74491	TTL-Logic	Synchronous Binary 10-Bit Up/Down	24-DIP		—
74491	TTL-Logic	Counter with Preset and Register	28-MP		—
74498	TTL-Logic	8-Bit Shift Register with parallel	24-DIP		—
74498	TTL-Logic	Input/Output, right/left w. Memory	28-MP		—
7450/1	TTL-Logic	Dual 2x2-Input AND/NOR	14-DIP		—
7450/1	TTL-Logic	Combination-Gate, 1 Gate expandable			—
7450/2	TTL-Logic	Dual 2x2-Input AND/NOR	14-DIP		—
7450/2	TTL-Logic	Combination-Gate, 1 Gate expandable			—
7450109	TTL-Logic	Dual Synchronous JK-Flip-Flop w.	16-DIP		—
7450109	TTL-Logic	Preset, Cleara. Complementary Outputs			—
74502	TTL-Logic	8-Bit Registar for Successive	16-DIP		—
74502	TTL-Logic	Approximation in A/D-Changer			—
74503	TTL-Logic	8-Bit Register for Successive	16-DIP		—
74503	TTL-Logic	Approximation in A/D-Changer with			—
74503	TTL-Logic	Expand			—
74504	TTL-Logic	12-Bit Register for Successive	14-DIP		—
74504	TTL-Logic	Approximation in A/D-Changer with			—
74504	TTL-Logic	Expand			—
7450728	TTL-Logic	Dual Synchronous D-Flip-Flop w.	14-DIP		—
7450728	TTL-Logic	Preset, Clear and Complementary			—
7450728	TTL-Logic	Outputs			—
7450729	TTL-Logic	Dual Synchronous D-Flip-Flop w.	14-DIP		—
7450729	TTL-Logic	Preset, Clear and Complementary			—
7450729	TTL-Logic	Outputs			—
745074	TTL-Logic	Dual Synchronous D-Flip-Flop w.	14-DIP		—
745074	TTL-Logic	Preset, Clear and Complementary			—
745074	TTL-Logic	Outputs			—
7451	CMOS/TTL	Dual AND/NOR Combination-Gate with	14-DIP		—
7451	Logic	2x2 Inputs	20-MP		—
7451/2	TTL-Logic	Dual AND/NOR Combination-Gate with	14-DIP		—
7451/2	TTL-Logic	2x2 Inputs			—
7451/3	TTL-Logic	Dual AND/NOR Combination-Gate with	14-DIP		—
7451/3	TTL-Logic	2x2 and 2x3 Inputs	20-MP		—
7451/4	TTL-Logic	Dual AND/NOR Combination-Gate with	14-DIP		—
7451/4	TTL-Logic	2x2 and 2x3 Inputs			—
74518	TTL-Logic	8-Bit Comparator, non inverting Output	20-DIP		—
74518	TTL-Logic		20-MP		—
74519	TTL-Logic	8-Bit Comparator, non inverting Output	20-DIP		—
74519	TTL-Logic		20-MP		—
7452/1	TTL-Logic	AND/OR Combination-Gate with 3x2 and	14-DIP		—
7452/1	TTL-Logic	1x3 Inputs, expandable			—
7452/2	TTL-Logic	AND/OR Combination-Gate with 3x2 and	14-DIP		—
7452/2	TTL-Logic	1x3 Inputs, expandable			—
74520	CMOS/TTL	8-Bit Comparator, inverting Output	20-DIP		—
74520	Logic		20-MP		—
74521	CMOS/TTL	8-Bit Comparator, inverting Output	20-DIP		—
74521	Logic		20-MP		—
74522	TTL-Logic	8-Bit Comparator, inverting Output	20-DIP		—
74522	TTL-Logic		20-MP		—
74524	TTL-Logic	8-Bit Register with Comparator	20-DIP		—

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745245	TTL-Logic	Quad Bus Transceiver, non inverting	20-DIP		—
74525	TTL-Logic	Binary 16-Bit Down Counter with Preset	28-DIP		—
74525	TTL-Logic		28-MP		—
74526	TTL-Logic	Programmable 16-Bit Comperetor	20-DIP		—
74526	TTL-Logic		20-MP		—
74527	TTL-Logic	Programmable 8-Bit- and 4-Bit	20-DIP		—
74527	TTL-Logic	Comparator	20-MP		—
74528	TTL-Logic	Programmable 12-Bit Comparator	16-DIP		—
74528	TTL-Logic		20-MP		—
7453/1	TTL-Logic	AND/NOR Combination-Gate 4x2 Inputs,	14-DIP		—
7453/1	TTL-Logic	expandeble			—
7453/2	TTL-Logic	AND/NOR Combination-Gate 4x2 Inputs,	14-DIP		—
7453/2	TTL-Logic	expandable			—
7453/3	TTL-Logic	AND/NOR Combination-Gate 3x2 and 1x3	14-DIP		—
7453/3	TTL-Logic	Inputs, expandable			—
7453/4	TTL-Logic	AND/NOR Combination-Gate 3x2 and 1x3	14-DIP		—
7453/4	TTL-Logic	Inputs, expandable			—
745300	TTL-Logic	LED-Driver for Fibre Opical Data Linee	8-DIP		—
74533	CMOS/TTL	8-Bit D-Latch with Eneble, inverting	20-DIP		—
74533	Logic		20-MP		—
74534	CMOS/TTL	8-Bit D-Latch with Eneble, inverting	20-DIP		—
74534	Logic		20-MP		—
74537	TTL-Logic	BCD-to-Dacimal Decoder	20-DIP		—
74538	TTL-Logic	3-Bit Binary Dacoder/Demultiplexer w.	20-DIP		—
74538	TTL-Logic	Add. Latch a. non invert. Outputs	20-MP		—
74539	TTL-Logic	Dual 2-Bit Binary	20-DIP		—
74539	TTL-Logic	Decoder/Demultiplexer	20-MP		—
7454/1	TTL-Logic	AND/NOR Combinabon-Gate With 4x2	14-DIP		—
7454/1	TTL-Logic	Inputs	20-MP		—
7454/2	TTL-Logic	AND/NOR Combination-Gate With 4x2	14-DIP		—
7454/2	TTL-Logic	Inputs			—
7454/3	TTL-Logic	AND/NOR Combination-Gate With 3x2 and	14-DIP		—
7454/3	TTL-Logic	1x3 Inputs			—
7454/4	TTL-Logic	AND/NOR Combination-Gate With 3x2 and	14-DIP		—
7454/4	TTL-Logic	1x3 Inputs			—
7454/5	TTL-Logic	AND/NOR Combinetion-Gate With 2x2 and	14-DIP		—
7454/5	TTL-Logic	2x3 Inputs	20-MP		—
7454/6	TTL-Logic	AND/NOR Combination-Gate With 2x2 and	14-DIP		—
7454/6	TTL-Logic	2x3 Inputs			—
74540	CMOS/TTL	8-Bit Bus Line Driver with 2 Enable	20-DIP		—
74540	Logic	Inputs, inverting	20-MP		—
74541	CMOS/TTL	Octal Bus Line Driver with 2 Enable	20-DIP		—
74541	Logic	Inputs, non inverting	20-MP		—
74543	CMOS/TTL	8-Bit Transceiver with Register, non	24-DIP		—
74543	Logic	inverting	28-MP		—
74544	CMOS/TTL	8-Bit Bi-Directional Bus Transceiver	24-DIP		—
74544	Logic	with Register, inverting	28-MP		—
74545	TTL-Logic	8-Bit Bi-Directional Bus Transceiver,	20-DIP		—
74545	TTL-Logic	non inverting	20-MP		—
74547	TTL-Logic	3-Bit Binary Decoder/Demultiplexer w.	20-DIP		—
74547	TTL-Logic	Addr. Register a. Quittance Input	20-MP		—
74548	TTL-Logic	3-Bit Binary Decoder/Demultiplexer	20-DIP		—
74548	TTL-Logic	with Quittance Input	20-MP		—
7455/1	TTL-Logic	2x4-Input AND/NOR Combination-Gate,	14-DIP		—
7455/1	TTL-Logic	expandeble			—
7455/2	TTL-Logic	2x4-Input AND/NOR Combination-Gate,	14-DIP		—
7455/2	TTL-Logic	expandable			—
7455/3	TTL-Logic	2x4-Input AND/NOR Combination-Gate	14-DIP		—
7455/3	TTL-Logic		20-MP		—
7455/4	TTL-Logic	2x4-Input AND/NOR Combination-Gate	14-DIP		—
74550	CMOS/TTL	6-Bit Transceiver with Register and	28-DIP		—
74550	Logic	Status-Flags, non inverting			—
74551	CMOS/TTL	6-Bit Transceiver with Register and	28-DIP		—
74551	Logic	Status-Flage, inverting			—
74552	TTL-Logic	8-Bit Transceiver w. Reg. Parity	28-DIP		—
74552	TTL-Logic	Gan/Check e Status-Flags, non	28-MP		—

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74552	TTL-Logic	inver.			—
745555	CMOS-Logic	Programmable Timer with Oscilletor	16-DIP		—
7456	TTL-Logic	Frequency Divider 50:1 (2:1, 5:1 and	8-DIP		—
7456	TTL-Logic	5:1)			—
74560	TTL-Logic	Synchronous Decimal Up/Down Counter	20-DIP		
74560	TTL-Logic	with Preset and Clear	20-MP		—
74561	TTL-Logic	Synchronous Binary 4-Bit Up Counter	20-DIP		—
74561	TTL-Logic	with Preset and Clear	20-MP		—
745620	TTL-Logic	8-Bit Bi-Directionel Bus Transceiver,	20-DIP		—
745620	TTL-Logic	inverting			—
74563	CMOS/TTL	8-Bit D-Latch with Enable, inverting	20-DIP		—
74563	Logic		20-MP		—
74564	CMOS/TTL	8-Bit D-Latch with Eneble, inverting	20-DIP		—
74564	Logic		20-MP		—
74568	CMOS/TTL	Synchronous Decimal Up/Down Counter	20-DIP		—
74568	Logic	with Preset and Clear			—
74569	CMOS/TTL	Synchronous Binary 4-Bit Up/Down	20-DIP		—
74569	Logic	Counter with Preset			—
7457	TTL-Logic	Frequency Divider 80: 1 (2:1, 5:1 and	8-DIP		—
7457	TTL-Logic	6:1)			—
74573	CMOS/TTL	6-Bit D-Latch with Enable, non	20-DIP		—
74573	Logic	inverting	20-MP		—
74574	CMOS/TTL	8-Bit D-Register with Eneble, non	20-DIP		—
74574	Logic	inverting	20-MP		—
74575	CMOS/TTL	8-Bit D-Register with Enable and	24-DIP		—
74575	Logic	Clear, non inverting			—
74576	CMOS/TTL	6-Bit D-Latch with Enable, inverting	20-DIP		—
74576	Logic				—
74577	TTL-Logic	8-Bit D-Regisler with Enable and	24-DIP		—
74577	TTL-Logic	Clear, inverting	26-MP		—
74579	TTL-Logic	Synchronous Binary 8-Bit Up/Down	20-DIP		—
74579	TTL-Logic	Counter with Preset			—
7456	CMOS-Logic	Dual AND/OR Combination-Gate	14-DIP		—
74560	CMOS/TTL	6-Bit D-Latch with Eneble, inverting	20-DIP		—
74560	Logic				—
74582	TTL-Logic	4-Bit Anthmebc/Logic Unit (ALU, BCD)	24-DIP		—
74563	CMOS/TTL	4-Bit BCD Adder	16-DIP		—
74563	Logic				—
74588	TTL-Logic	6-Bit Transceiver for IEEE-68 Bue	20-DIP		—
74589	CMOS-Logic	8-Bit Shift Register with Input Latch	16-DIP		
74590	CMOS/TTL	Asynchronous Binery 6-Bit Up Counter	16-DIP		—
74590	Logic	with Output Register	20-MP		—
74591	TTL-Logic	Asynchronous Binary 8-Bit Up Counter	16-DIP		—
74591	TTL-Logic	with Output Register	20-MP		—
74592	CMOS/TTL	Asynchronous Binary 8-Bit Up Counter	16-DIP		—
74592	Logic	with Input Register and Preset			—
74593	CMOS/TTL	Asynchronous Binary 8-Bit Up Counter	16-DIP		—
74593	Logic	with Input Register and Preset			—
74594	CMOS/TTL	8-Bit Shift Register with Output Latch	16-DIP		—
74594	Logic		20-MP		—
74595	CMOS/TTL	6-Bit Shift Register with Output Latch	16-DIP		—
74595	Logic		20-MP		—
74596	TTL-Logic	6-Bit Shift Register with Output Latch	16-DIP		—
74596	TTL-Logic		20-MP		—
74597	CMOS/TTL	8-Bit Shift Register with parallel	16-DIP		—
74597	Logic	Input/Output and Input Latch	20-MP		—
74596	TTL-Logic	8-Bit Shift Register with parallel	16-DIP		—
74596	TTL-Logic	Input/Output and Input Latch	20-MP		—
74599	TTL-Logic	8-Bit Shift Register with Output Latch	16-DIP		—
74599	TTL-Logic		20-MP		—
7460/1	TTL-Logic	Dual 4-Input AND Expander for 7423,	14-DIP		—
7460/1	TTL-Logic	7450, 7453, 7455			—
7460/2	TTL-Logic	Dual 4-Input AND Expander for 7423,	14-DIP		—
7460/2	TTL-Logic	7450, 7453, 7455			—
74600	TTL-Logic	Refresh Controller for 4/16 KByte	20-DIP		—
74600	TTL-Logic	Dynamic RAMs			—

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74601	TTL-Logic	Refresh Controller for 64 KByte	20-DIP		—
74601	TTL-Logic	Dynamic RAMs			—
74602	TTL-Logic	Refresh Controller for 4/16 KByte	20-DIP		—
74602	TTL-Logic	Dynamic RAMs			—
74603	TTL-Logic	Refresh Controller for 64 KByte	20-DIP		—
74603	TTL-Logic	Dynamic RAMs			—
74604	CMOS/TTL	Octal 2-to-1 Bus Multiplexer with	28-DIP		—
74604	Logic	Latch	28-MP		—
74605	TTL-Logic	Octal 2-to-1 Bus Multiplexer with	40-DIP		—
74605	TTL-Logic	Latch			—
74606	TTL-Logic	Octal 2-to-1 Bus Multiplexer with	40-DIP		—
74606	TTL-Logic	Latch	28-MP		—
74607	TTL-Logic	Octal 2-to-1 Bus Multiplexer with	40-DIP		—
74607	TTL-Logic	Latch	26-MP		—
74608	TTL-Logic	Cycle Controller for Dynamic RAMs	16-DIP		—
7461/1	TTL-Logic	Triple 3-Input AND Expander for 74H52	14-DIP		—
7461/2	TTL-Logic	Triple 3-Input AND Expander for 74H52	14-DIP		—
74610	TTL-Logic	Memory Mepper for Expanding from 4 to	64-DIP		—
74610	TTL-Logic	12 Address-Lines with Latch			—
74611	TTL-Logic	Memory Mapper for Expanding from 4 to	64-DIP		—
74611	TTL-Logic	12 Address-Lines with Latch			—
74612	TTL-Logic	Memory Mapper for Expanding from 4 to	64-DIP		—
74612	TTL-Logic	12 Address-Lines			—
74613	TTL-Logic	Memory Mapper for Expanding from 4 to	64-DIP		—
74613	TTL-Logic	12 Address-Lines			—
74614	TTL-Logic	8-Bit Bus Transceiver with	24-DIP		—
74614	TTL-Logic	Bi-Directional Registers, inverting	28-MP		—
74615	TTL-Logic	8-Bit Bi-Directional Bus Transceiver	24-DIP		—
74615	TTL-Logic	with Register, non inverting	28-MP		—
74616	TTL-Logic	16-Bit Parallel Error-Detecting and	40-DIP		—
74616	TTL-Logic	Correcting Element (EDAC)	44-MP		—
74617	TTL-Logic	16-Bit Perallel Error-Detecting and	40-DIP		—
74617	TTL-Logic	Correcting Element (EDAC)	44-MP		—
7462/1	TTL-Logic	AND/OR Expander for 74H50, 74H53,	14-DIP		—
7462/t	TTL-Logic	74H55			—
7462/2	TTL-Logic	AND/OR Expander for 74H50, 74H53,	14-DIP		—
7462/2	TTL-Logic	74H55			—
74620	CMOS/TTL	8-Bit Bi-Directional Bus Driver with	20-DIP		—
74620	Logic	Register, inverting	20-MP		—
74621	TTL-Logic	8-Bit Bi-Directional Bus Transceiver	20-DIP		—
74621	TTL-Logic	with Register, non inverting	20-MP		—
74622	TTL-Logic	6-Bit Bi-Directional Bus Driver with	20-DIP		—
74622	TTL-Logic	Register, inverting	20-MP		—
74623	CMOS/TTL	8-Bit Bi-Directional Bus Transceiver	20-DIP		—
74623	Logic	with Register, non inverting	20-MP		—
74624	TTL-Logic	Voltage-Controlled Oscillator with	14-DIP		—
74624	TTL-Logic	Enable and Complementary Outputs	20-MP		—
74625	TTL-Logic	Dual Voltage-Controlled Oscillator	16-DIP		—
74625	TTL-Logic	with Complementary Outputs	20-MP		—
74628	TTL-Logic	Dual Voltage-Controlled Oscillator	18-DIP		—
74628	TTL-Logic	with Enable and Complementary Outputs	20-MP		—
74627	TTL-Logic	Dual Voltage-Controllad Oscilletor	14-DIP		—
74627	TTL-Logic		20-MP		—
74628	TTL-Logic	Voltage-Controlled Oscillator with	14-DIP		—
74628	TTL-Logic	Enable	20-MP		—
74629	TTL-Logic	Dual Voltage-Controlled Oscillator	16-DIP		—
74629	TTL-Logic	with Enable	20-MP		—
7463	TTL-Logic	Quad Current Sensor	14-DIP		—
74630	TTL-Logic	16-Bit Parallel Error-Detecting end	40-DIP		—
74630	TTL-Logic	Correcting Element (EDAC)	28-MP		—
74631	TTL-Logic	16-Bit Perallel Error-Detecting and	40-DIP		—
74631	TTL-Logic	Correcting Element (EDAC)	28-MP		—
74632	TTL-Logic	32-Bit Error-Detecting and Correcting	52-DIP		—
74632	TTL-Logic	Element (EDAC)	52-MP		—
746323	CMOS-Logic	Asynchronous Binary 3-Bit Up Counter	8-DIP		—
746323	CMOS-Logic	with Oscillator			—

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74633	TTL-Logic	32-Bit Error-Detecting and Correcting	52-DIP		—
74633	TTL-Logic	Element (EDAC)	68-MP		—
74634	TTL-Logic	32-Bit Error-Detecting and Correcting	52-DIP		—
74634	TTL-Logic	Element (EDAC)	68-MP		—
74635	TTL-Logic	32-Bit Error-Detecting and Correcting	46-DIP		—
74635	TTL-Logic	Element (EDAC)	68-MP		—
74636	TTL-Logic	8-Bit Error-Detecting and Correcting	20-DIP		—
74636	TTL-Logic	Element (EDAC)	20-MP		—
74637	TTL-Logic	8-Bit Error-Detecting and Correcting	20-DIP		—
74637	TTL-Logic	Element(EDAC)	20-MP		—
74636	TTL-Logic	8-Bit Bi-Directional Bus Transceiver,	20-DIP		—
74638	TTL-Logic	inverting	20-MP		—
74639	TTL-Logic	8-Bit Bi-Directional Bus Transceiver,	20-DIP		—
74639	TTL-Logic	non inverting	20-MP		—
7464	TTL-Logic	AND/NOR Combination-Gate with 2x2,	14-DIP		—
7464	TTL-Logic	1x3 and 1x4 Inputs	20-MP		—
74640	CMOS/TTL	8-Bit Bi-Directional Bus Transceiver,	20-DIP		—
74640	Logic	inverting	20-MP		—
74641	TTL-Logic	8-Bit Bi-Directional Bus Transceiver,	20-DIP		—
74641	TTL-Logic	non inverting	20-MP		—
74642	TTL-Logic	8-Bit Bi-Directional Bus Transceiver,	20-DIP		—
74642	TTL-Logic	inverting	20-MP		—
74643	CMOS/TTL	8-Bit Bi-Directional Bus Transceiver,	20-DIP		—
74643	Logic	inverting/non inverting	20-MP		—
74644	TTL-Logic	8-Bit Bi-Directional Bus Transceiver,	20-DIP		—
74644	TTL-Logic	inverting/non inverting	20-MP		—
74645	CMOS/TTL	8-Bit Bi-Directional Bus Transceiver,	20-DIP		—
74645	Logic	non inverting	20-MP		—
74646	CMOS/TTL	8-Bit Bus-Transceiver with	24-DIP		—
74646	Logic	Bi-Directional Registers, non	28-MP		—
74648		inverting			—
74647	CMOS/TTL	8-Bit Bus-Transceiver with	24-DIP		—
74647	Logic	Bi-Directional Registers, non			—
74647		inverting			—
74648	CMOS/TTL	8-Bit Bus Transceiver with	24-DIP		—
74648	Logic	Bi-Directional Registers, inverting	28-MP		—
74649	CMOS/TTL	8-Bit Bus Transceiver with	24-DIP		—
74649	Logic	Bi-Directional Registers, inverting			—
7465	TTL-Logic	AND/NOR Combination-Gate with 2x2,	14-DIP		—
7465	TTL-Logic	1x3 and 1x4 Inputs	20-MP		—
74651	CMOS/TTL	8-Bit Bi-Directional Bus Transceiver	24-DIP		—
74651	Logic	with Register, inverting	28-MP		—
74652	CMOS/TTL	8-Bit Bi-Directional Bus Transceiver	24-DIP		—
74652	Logic	with Register, non inverting	28-MP		—
74653	CMOS/TTL	8-Bit Bi-Directional Bus Transceiver	24-DIP		—
74653	Logic	with Register, inverting			—
74654	CMOS/TTL	8-Bit Bi-Directional Bus Transceiver	24-DIP		—
74654	Logic	with Register, non inverting			—
74655	TTL-Logic	8-Bit Bus Driver with Parity	24-DIP		—
74655	TTL-Logic	Ganerator/Parity Checker, inverting			—
74656	TTL-Logic	8-Bit Bus Driver with Parity	24-DIP		—
74656	TTL-Logic	Generator/Parity Checker, non			—
74656	TTL-Logic	inverting			—
74657	TTL-Logic	8-Bit Transceiver with Parity	24-DIP		—
74657	TTL-Logic	Generator/Checker, non inverting	28-MP		—
74658	CMOS-Logic	8-Bit Bus Transceiver with Parity	24-DIP		—
74656	CMOS-Logic	Generator, inverting	28-MP		—
74659	CMOS-Logic	8-Bit Transceiver with Parity	24-DIP		—
74659	CMOS-Logic	Generator/Checker, non inverting	28-MP		—
74664	CMOS-Logic	8-Bit Bus Transceiver with Parity	24-DIP		—
74664	CMOS-Logic	Ganerator, inverting	28-MP		—
74665	CMOS-Logic	8-Bit Transceiver with Parity	24-DIP		—
74665	CMOS-Logic	Generator/Checker, non inverting	28-MP		—
74666	TTL-Logic	8-Bit Transparent D-Latch with Read	24-DIP		—
74666	TTL-Logic	Back, non inverting	28-MP		—
74667	TTL-Logic	8-Bit Transparent D-Latch with Read	24-DIP		—

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74667	TTL-Logic	Back, inverting	28-MP		—
74668	CMOS/TTL	Synchronous Decimal Up/Down Counter	16-DIP		—
74668	Logic	with Preset			—
74668	CMOS/TTL	Synchronous Binary 4-Bit Up/Down	16-DIP		—
74669	Logic	Counter with Preset			—
74670	CMOS/TTL	4x4-Bit Random Access Memory (RAM)	16-DIP		—
74670	Logic		20-MP		—
74671	TTL-Logic	4-Bit Universsl Shift Register with	20-DIP		—
74671	TTL-Logic	eynchronous Clear	20-MP		—
74672	TTL-Logic	4-Bit Universal Shift Register with	20-DIP		—
74672	TTL-Logic	synchronous Clear	20-MP		—
74673	CMOS/TTL	16-Bit Shift Register with parallel	24-DIP		—
74673	Logic	Outputs			—
74674	CMOS/TTL	16-Bit Shift Register with parellel	24-DIP		—
74674	Logic	Inputs			—
74675	TTL-Logic	16-Bit Shift Register with parallel	24-DIP		—
74675	TTL-Logic	Outputs			—
74676	TTL-Logic	16-Bit Shitt Register with parallel	24-DIP		—
74676	TTL-Logic	Inputs	28-MP		—
74677	CMOS/TTL	16-Bit Address Comparator with Enable	24-DIP		—
74677	Logic	16-Bit Address Comparator with Eneble	24-DIP		—
74678	CMOS/TTL	16-Bit Address Comparator with	24-DIP		—
74676	Logic	Register	28-MP		—
74679	CMOS/TTL	12-Bit Address Comparator with Enable	20-DIP		—
74679	Logic		20-MP		—
7466	TTL-Logic	Dual Asynchronous Decimal Up Counter	16-DIP		—
7466	TTL-Logic		20-MP		—
74680	CMOS/TTL	12-Bit Address Comparator with	20-DIP		—
74680	Logic	12-Bit Address Comparator with	20-DIP		—
74681	TTL-Logic	4-Bit Accumulator	20-DIP		—
74681	TTL-Logic		20-MP		—
74682	CMOS/TTL	6-Bit Comparator with Internal Pull-Up	20-DIP		—
74682	Logic		20-MP		—
74683	TTL-Logic	6-Bit Comparator with Internal Pull-Up	20-DIP		—
74683	TTL-Logic		20-MP		—
74684	CMOS/TTL	6-Bit Comparator	20-DIP		—
74684	Logic		20-MP		—
74685	TTL-Logic	8-Bit Comparator	20-DIP		—
74685	TTL-Logic		20-MP		—
74668	CMOS/TTL	8-Bit Comparator with Output-Eneble	24-DIP		—
74686	Logic				—
74687	TTL-Logic	8-Bit Comparator with Output-Enable	24-DIP		—
74667	TTL-Logic		28-MP		—
74666	CMOS/TTL	8-Bit Comparator with Output-Enable	20-DIP		—
74668	Logic		20-MP		—
74689	TTL-Logic	8-Bit Comparator with Output-Enable	20-DIP		—
74689	TTL-Logic		20-MP		—
7469	TTL-Logic	Dual Asynchronous Binery 4-Bit Up	16-DIP		—
7469	TTL-Logic	Counter	20-MP		—
74690	CMOS/TTL	Synchronous Decimal Up Countar with	20-DIP		—
74690	Logic	Presst, Register and Multiplexer	20-MP		—
74691	CMOS/TTL	Synchronous Bin 4-Bit Up Counter	20-DIP		—
74691	Logic	with Preset, Register and Multiplexer	20-MP		—
74692	CMOS/TTL	Synchronous Decimal Up Counter with	20-DIP		—
74692	Logic	Presst, Register and Multiplexer	20-MP		—
74693	CMOS/TTL	Synchronous Bin 4-Bit Up Counter	20-DIP		—
74693	Logic	with Preset, Register and Multiplexer	20-MP		—
74696	CMOS/TTL	Asynchronous Decimal Up Counter with	20-DIP		—
74696	Logic	Preset, Register and Multiplexer	20-MP		—
74697	CMOS/TTL	Sync Binary 4-Bit Up/Down Counter	20-DIP		—
74697	Logic	with Preset, Register a. Multiplexer	20-MP		—
74698	CMOS/TTL	Synchronous Deci. Up/Down Counter	20-DIP		—
74696	Logic	with Preset, Register and Multiplexer	20-MP		—
74699	CMOS/TTL	Sync Binary 4-Bit Up/Down Counter	20-DIP		—
74699	Logic	with Preset, Ragister a. Multiplexer	20-MP		—
7470/1	TTL-Logic	Positive Edge Triggered JK Flip-Flop	14-DIP		—

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7470/1	TTL-Logic	with AND Inputs, Preset and Clear			—
7470/2	TTL-Logic	Positive Edge Triggered JK Flip-Flop	14-DIP		—
7470/2	TTL-Logic	with AND Inputs, Preset and Clear			—
747001	CMOS-Logic	Quad 2-Input AND Schmitt Trigger	14-DIP		—
747001	CMOS-Logic		20-MP		—
747002	CMOS-Logic	Quad 2-Input NOR Schmitt Trigger	14-DIP		—
747002	CMOS-Logic		20-MP		—
747006	CMOS-Logic	Dual NAND Gate, Dual NOR Gate, 2	24-DIP		—
747006	CMOS-Logic	Inverters	28-MP		—
747007	CMOS-Logic	Hex Buffer/TTL Driver, non inverting	14-DIP		—
747007	CMOS-Logic		20-MP		—
747008	CMOS-Logic	Dual NAND Gate, Dual NOR Gate, 2	24-DIP		—
747008	CMOS-Logic	Inverters	28-MP		—
747022	CMOS-Logic	Synchronous Octal Counter decoded	16-DIP		—
747022	CMOS-Logic	Outputs	20-MP		—
747030	CMOS-Logic	16x9-Bit FIFO	28-DIP		—
747032	CMOS-Logic	Quad 2-Input OR-Schmitt-Trigger	14-DIP		—
747032	CMOS-Logic		20-MP		—
747038	CMOS-Logic	8-Bit Bi-Directional Bus Transceiver	24-DIP		—
747038	CMOS-Logic	with Latch			—
747046	CMOS-Logic	Phase-Locked-Loop Switcher(PLL)	16-DIP		—
747060	CMOS-Logic	Asynchronous Binary 14-Bit Up Counter	20-DIP		—
747060	CMOS-Logic	with Internal Oscillator			—
747061	CMOS-Logic	Asynchronous Binary 14-Bit Up Counter	20-DIP		—
747061	CMOS-Logic	with Internal Oscillator			—
747074	CMOS-Logic	2 Inverters, 1 NAND Gate, 1 NOR Gate,	24-DIP		—
747074	CMOS-Logic	2 Flip-Flops	28-MP		—
747075	CMOS-Logic	2 Inverters, 1 NAND Gate, 1 NOR Gate,	24-DIP		—
747075	CMOS-Logic	2 Flip-Flops	26-MP		—
747076	CMOS-Logic	2 Inverters, 1 NAND Gate, 1 NOR Gate,	24-DIP		—
747076	CMOS-Logic	2 Flip-Flops	26-MP		—
74708	CMOS-Logic	16x9-Bit FIFO	28-DIP		—
747080	CMOS-Logic	16-Bit Parity Checker	20-DIP		—
7471/1	TTL-Logic	2x2-Input Pulse Triggered JK	14-DIP		—
7471/1	TTL-Logic	Flip-Flop with Preset			—
7471/2	TTL-Logic	2x2-Input Pulse Triggered JK	14-DIP		—
7471/2	TTL-Logic	Flip-Flop with Preset			—
7471/3	TTL-Logic	3-Input Pulse Triggered JK Flip-Flop	14-DIP		—
7471/3	TTL-Logic	with Preset			—
7471/4	TTL-Logic	3-Input Pulse Triggered JK Flip-Flop	14-DIP		—
7471/4	TTL-Logic	with Preset			—
74711	TTL-Logic	Pental 2-to-1 Data	20-DIP		—
74711	TTL-Logic	Selector/Multiplexer			—
74712	TTL-Logic	Pental 3-to-1 Data	24-DIP		—
74712	TTL-Logic	Selector/Multiplexer			—
74716	TTL-Logic	4-Bit Decimal Down Counter with Preset	16-DIP		—
74716	TTL-Logic		20-MP		—
74716	TTL-Logic	4-Bit Binary Down Counter with Preset	16-DIP		—
74718	TTL-Logic		20-MP		—
74719	TTL-Logic	4-Bit Binary Down Counter with Preset	16-DIP		—
74719	TTL-Logic		20-MP		—
7472/1	TTL-Logic	3-Input Positive Pulse Triggered JK	14-DIP		—
7472/1	TTL-Logic	Flip-Flop with Preset and Clear			—
7472/2	TTL-Logic	3-Input Positive Pulse Triggered JK	14-DIP		—
7472/2	TTL-Logic	Flip-Flop with Preset and Clear			—
747200	CMOS-Logic	256x9-Bit FIFO	28-DIP		—
747200	CMOS-Logic		32-MP		—
747203	CMOS-Logic	2048x9-Bit FIFO	28-DIP		—
747203	CMOS-Logic		32-MP		—
747204	CMOS-Logic	4096x9-Bit FIFO	26-DIP		—
747204	CMOS-Logic		32-MP		—
7472211	CMOS-Logic	512x9-Bit Clocked FIFO	32-MP		—
7472221	CMOS-Logic	1024x9-Bit Clocked FIFO	32-MP		—
7472231	CMOS-Logic	2048x9-Bit Clocked FIFO	32-MP		—
7472241	CMOS-Logic	4096x9-Bit Clocked FIFO	32-MP		—
74723/1	TTL-Logic	Quad 3-to-1 Data Selector/Multiplexer	24-DIP		—

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74723/2	CMOS-Logic	64x9-Bit FIFO	28-DIP		—
74724	TTL-Logic	Voltage-Controlled Oscillator with	8-DIP		—
74724	TTL-Logic	Output Stage			—
747240	CMOS-Logic	Octal Bus Line Driver with Schmitt	20-DIP		—
747240	CMOS-Logic	Trigger Inputs, inverting			—
747241	CMOS-Logic	Octal Bus Line Driver with Schmitt	20-DIP		—
747241	CMOS-Logic	Trigger inputs, non inverting			—
747244	CMOS-Logic	Octal Bus Line Driver with Schmitt	20-DIP		—
747244	CMOS-Logic	Trigger inputs, non inverting			—
747245	CMOS-Logic	Quad Bus Transceiver with Schmitt	20-DIP		—
747245	CMOS-Logic	Trigger Inputs, non inverting			—
74725/1	TTL-Logic	Quad 4-to-1 Data Selector/Multiplexer	24-DIP		—
74725/2	CMOS-Logic	512x9-Bit FIFO	28-DIP		—
747266	CMOS-Logic	Quad 2-Input EX-NOR Gate	14-DIP		—
747266	CMOS-Logic		20-MP		—
747292	CMOS-Logic	Programmable 32-Bit Binary Frequency	18-DIP		—
747292	CMOS-Logic	Divider	20-MP		—
747294	CMOS-Logic	Programmable 16-Bit Binary Frequency	16-DIP		—
747294	CMOS-Logic	Divider	20-MP		—
7473	CMOS/TTL	Dual JK Flip-Flop with Clear	14-DIP		—
7473	Logic		20-MP		—
74732	TTL-Logic	Quad 2-to-1 Data Multiplexer (Bus	20-DIP		—
74732	TTL-Logic	Multiplexer), inverting			—
74733	TTL-Logic	Quad 2-to-1 Data Multiplexer (Bus	20-DIP		—
74733	TTL-Logic	Multiplexer), non inverting			—
7474	CMOS/TTL	Dual D-Flip-Flop with Complementary	14-DIP		—
7474	Logic	Outputs With Preset and Clear	20-MP		—
7474/2	TTL-Logic	Dual D-Flip-Flop with Complementary	14-DIP		—
7474/2	TTL-Logic	Outputs With Preset and Clear			—
747403	CMOS-Logic	64x4-Bit FIFO	16-DIP		—
747404	CMOS-Logic	64x5-Bit FIFO	20-DIP		—
74746	TTL-Logic	Octal Line Driver with Pull-Up	20-DIP		—
74746	TTL-Logic	Input-Resistor, inverting	20-MP		—
74747	TTL-Logic	Octal Line Driver with Pull-Up Input	20-DIP		—
74747	TTL-Logic	Resistor, non inverting	20-MP		—
74748	TTL-Logic	3-Bit Binary Priority Encoder	16-DIP		—
7475	CMOS/TTL	Dual 2-Bit D-Latch with Complementary	16-DIP		—
7475	Logic	Outputs	20-MP		—
747540	CMOS-Logic	Octal Buffer/Driver with Schmitt	20-DIP		—
747540	CMOS-Logic	Trigger Inputs, inverting			—
747541	CMOS-Logic	Octal Buffer/Driver with Schmitt	20-DIP		—
747541	CMOS-Logic	Trigger Inputs, non inverting			—
74755	TTL-Logic	8-Bit Mailbox Register with Ready Flag	24-DIP		—
74756	TTL-Logic	Octal 4-Bit Line Driver with Seperata	20-DIP		—
74756	TTL-Logic	Enable Inputs, inverting	20-MP		—
74757	TTL-Logic	Octal 4-Bit Line Driver with Seperata	20-DIP		—
74757	TTL-Logic	Enable Inputs, non inverting	20-MP		—
74756	TTL-Logic	Quad Bi-Directional Bus Line Driver,	14-DIP		—
74756	TTL-Logic	inverting	20-MP		—
74759	TTL-Logic	Quad Bi-Directional Bus Line Driver,	14-DIP		—
74759	TTL-Logic	non inverting	20-MP		—
747597	CMOS-Logic	8-Bit Shift Register with Input Latch	16-DIP		—
7476	CMOS/TTL	Dual JK Flip-Flops with Preset and	16-DIP		—
7476	Logic	Clear	20-MP		—
74760	TTL-Logic	Octal 4-Bit Line Driver with Seperate	20-DIP		—
74760	TTL-Logic	Enable Inputs, non inverting	20-MP		—
74762	TTL-Logic	Quad Line Driver, 4 inverting, 4 non	20-DIP		—
74762	TTL-Logic	inverting, with Separat Enable	20-MP		—
747623	CMOS-Logic	8-Bit Bi-Directional Bus Driver with	20-DIP		—
747623	CMOS-Logic	OC- and TS-Output, non inverting			—
74763	TTL-Logic	Octal 4-Bit Line Driver with Seperate	20-DIP		—
74763	TTL-Logic	Enable Inputs, inverting	20-MP		—
74764	TTL-Logic	Multifunction Controller for Dynamic	40-DIP		—
74764	TTL-Logic	RAMs	44-MP		—
74765	TTL-Logic	Multifunction Controller for Dynamic	40-DIP		—
74765	TTL-Logic	RAMs	44-MP		—

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747651	CMOS-Logic	8-Bit Bus Transceiver with Register,	24-DIP		—
747651	CMOS-Logic	inverting			—
7477	CMOS-Logic	Dual 2-Bit D-Latch	14-DIP		—
7477	TTL-Logic	Dual 2-Bit D-Latch	14-DIP		—
7477	CMOS-Logic		20-MP		—
747731	CMOS-Logic	Quad 64-Bit Serial Shift Register	16-DIP		—
74776	TTL-Logic	8-Bit Transceiver with Register	28-DIP		—
74776	TTL-Logic	(Pi-/Future-Bus)	28-MP		—
74777	TTL-Logic	Triple Bus Transceiver with Register	20-DIP		—
74777	TTL-Logic	(TM-Bus)	20-MP		—
74779	TTL-Logic	Synchronous Binary 8-Bit Up/Down	16-DIP		—
74779	TTL-Logic	Counter with Preset			—
7478	CMOS/TTL	Dual JK Flip-Flops with Common Clock,	14-DIP		—
7478	Logic	Preset and Clear			—
7478/2	TTL-Logic	Dual JK Flip-Flops with Common Clock,	14-DIP		—
7478/2	TTL-Logic	Preset and Clear	20-MP		—
747801	CMOS-Logic	1024x18-Bit Clocked FIFO	80-DIP		—
747801	CMOS-Logic		68-MP		—
747802	CMOS-Logic	1024x18-Bit FIFO	68-MP		—
747803	CMOS-Logic	512x18-Bit Clocked FIFO	56-DIP		—
747804	CMOS-Logic	512x18-Bit FIFO	56-DIP		—
747805	CMOS-Logic	258x18-Bit Clocked FIFO	56-DIP		—
747806	CMOS-Logic	256x18-Bit FIFO	56-DIP		—
747807	CMOS-Logic	2048x9-Bit Clocked FIFO	84-DIP		—
747807	CMOS-Logic		44-MP		—
747808	CMOS-Logic	2048x9-Bit FIFO	64-DIP		—
747808	CMOS-Logic		44-MP		—
747811	CMOS-Logic	1024x18-Bit Clocked FIFO	80-DIP		—
747811	CMOS-Logic		68-MP		—
747813	CMOS-Logic	64x18-Bit Clocked FIFO	56-DIP		—
747814	CMOS-Logic	64x18-Bit Clocked FIFO	56-DIP		—
747815	CMOS-Logic	64x36x2-Bit Clocked FIFD	120-DIP		—
747819	CMOS-Logic	512x18x2-Bit Clocked Bidirectional	80-DIP		—
747819	CMOS-Logic	FIFOs			—
747820	CMOS-Logic	512x18x2-Bit Bidirectional FIFOs	80-DIP		—
747821	CMOS-Logic	512x38x2-Bit Clocked FIFO	120-DIP		—
747822	CMOS-Logic	512x36x2-Bit Clocked FIFO	120-DIP		—
747823	CMOS-Logic	1024x36-Bit Clocked FIFO	120-DIP		—
74783	TTL-Logic	Synchronous Address Multiplexer (=MC	40-DIP		—
74783	TTL-Logic	6883)			—
74764	TTL-Logic	8-Bit Serial/Parallel Multiplier	20-DIP		—
74784	TTL-Logic	(with Adder/Subtracteur)			—
74785	TTL-Logic	Synchronous Address Multiplexer (=MC	40-DIP		—
74785	TTL-Logic	6883)			—
74768	TTL-Logic	Asynchronous Bus Arbiter	16-DIP		—
74795	TTL-Logic	Octal Buffer with Common Enable, non	20-DIP		—
74795	TTL-Logic	inverting			—
74796	TTL-Logic	Octal Buffer with Common Enable,	20-DIP		—
74796	TTL-Logic	inverting			—
74797	TTL-Logic	Dual 4-Bit Buffer with Separate	20-DIP		—
74797	TTL-Logic	Enable Inputs, non inverting			—
74796	TTL-Logic	Dual 4-Bit Buffer with Separata	20-DIP		—
74796	TTL-Logic	Enable Inputs, inverting			—
7480/1	TTL-Logic	1-Bit Full Adder with Complementary	14-DIP		—
7480/1	TTL-Logic	Inputs/Outputs and Parallel Carry			—
7480/2	TTL-Logic	1-Bit Full Adder with Complementary	14-DIP		—
7480/2	TTL-Logic	Inputs/Outputs and Parallel Carry			—
74800	TTL-Logic	Triple 4-Input AND/NAND Driver	20-DIP		—
74800	TTL-Logic		20-MP		—
748003	TTL-Logic	Dual 2-Input NAND Gate	8-DIP		—
748003	TTL-Logic		20-MP		—
74802	TTL-Logic	Triple 4-Input OR/NOR Driver	20-DIP		—
74802	TTL-Logic		20-MP		—
74803	TTL-Logic	Quad D-Flip-Flop with Clockdriver and	14-DIP		—
74803	TTL-Logic	Outputdriver, non inverting	20-MP		—
74804	CMOS/TTL	Hex 2-Input NAND Driver	20-DIP		—

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74804	Logic		20-MP		—
74805	CMOS/TTL	Hex2-Input NOR Driver	20-DIP		—
74805	Logic		20-MP		—
74807	TTL-Logic	8-Bit Transceiver with Shift-,	28-DIP		—
74807	TTL-Logic	Adder-, Parity-, Count-Functions	28-MP		—
74808	CMOS/TTL	Hex2-Input AND Driver	20-DIP		—
74808	Logic		20-MP		—
7481	TTL-Logic	16x1-Bit RAM	14-DIP		—
74810	TTL-Logic	Quad 2-Input EX-NOR Gate	14-DIP		—
74810	TTL-Logic		20-MP		—
74811	TTL-Logic	Quad 2-Input EX-NOR Gate	14-DIP		—
74811	TTL-Logic		20-MP		—
74812	TTL-Logic	2-Bit Binary Decoder/Demultiplexer	24-DIP		—
74812	TTL-Logic	and programmable 12-Bit Comparator	28-MP		—
748161	TTL-Logic	Synchronous Binary 8-Bit Up Counter	24-DIP		—
748161	TTL-Logic	with Preset	28-MP		—
748163	TTL-Logic	Synchronous Binary 8-Bit Up Counter	24-DIP		—
748163	TTL-Logic	with Preset	28-MP		—
748169	TTL-Logic	Sync. Binary 8-Bit Up/Down Counter	24-DIP		—
748169	TTL-Logic	with Preset and Asynchronous Clear	28-MP		—
74818	CMOS-Logic	8-Bit Multifunction Register	24-DIP		—
74818	CMOS-Logic		28-MP		—
74819	TTL-Logic	8-Bit Multifunction Register	24-DIP		—
74819	TTL-Logic		28-MP		—
7482	TTL-Logic	2-Bit Full Adder	14-DIP		—
74821	CMOS/TTL	10-Bit D-Register, non inverting	24-DIP		—
74821	Logic		28-MP		—
74822	CMOS/TTL	10-Bit D-Register, inverting	24-DIP		—
74822	Logic				—
74823	CMOS/TTL	9-Bit D-Register with Clockenable and	24-DIP		—
74823	Logic	Clear, non inverting			—
74824	CMOS/TTL	9-Bit D-Register with Clockenable and	24-DIP		—
74824	Logic	Clear, inverting			—
74825	CMOS/TTL	8-Bit D-Register with Clockenable and	24-DIP		—
74825	Logic	Clear, non inverting			—
74826	CMOS/TTL	8-Bit D-Register with Clockenable and	24-DIP		—
74826	Logic	Clear, inverting			—
74827	CMOS/TTL	10-Bit Bus Driver, non inverting	24-DIP		—
74827	Logic				—
74828	CMOS/TTL	10-Bit Bus Driver, inverting	24-DIP		—
74826	Logic				—
7483	CMOS/TTL	4-Bit Full Adder	16-DIP		—
7483	Logic				—
74832	CMOS/TTL	Hex2-Input OR Driver	20-DIP		—
74832	Logic		20-MP		—
74835	TTL-Logic	8-Bit Shift Register with 2x8-Bit	24-DIP		—
74835	TTL-Logic	Inputs and Input-Multiplexer			—
74838	TTL-Logic	Micro Programm Sequence Controller	20-DIP		—
7484	TTL-Logic	16x1-Bit RAM	16-DIP		—
74841	CMOS/TTL	10-Bit D-Latch, non inverting	24-DIP		—
74841	Logic				—
74842	CMOS/TTL	10-Bit D-Latch with Enable, inverting	24-DIP		—
74842	Logic				—
74843	CMOS/TTL	9-Bit D-Latch with Preset and Clear,	24-DIP		—
74843	Logic	non inverting	28-MP		—
74844	CMOS/TTL	9-Bit D-Latch with Preset and Clear,	24-DIP		—
74844	Logic	inverting			—
74845	CMOS/TTL	8-Bit D-Latch with 3-Enable-Inputs,	24-DIP		—
74845	Logic	Preset and Clear, non inverting			—
74846	CMOS/TTL	8-Bit D-Latch with 3-Enable-Inputs,	24-DIP		—
74848	Logic	Preset and Clear, inverting			—
74848	TTL-Logic	3-Bit Binary Priority Encoder	16-DIP		—
7485	CMOS/TTL	4-Bit Comparator	18-DIP		—
7485	Logic		20-MP		—
7485/2	TTL-Logic	4-Bit Comparator	16-DIP		—
74850	TTL-Logic	16-to-1 Data Selector/Multiplexer	40-DIP		—

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74850	TTL-Logic		28-MP		—
74851	TTL-Logic	18-to-1 Data Selector/Multiplexer	40-DIP		—
74851	TTL-Logic		28-MP		—
74852	TTL-Logic	Universal Bi-Directional 8-Bit Port	24-DIP		—
74852	TTL-Logic	Controller	28-MP		—
74856	TTL-Logic	Universal Bi-Directional 8-Bit Port	24-DIP		—
74856	TTL-Logic	Controller	28-MP		—
74857	TTL-Logic	Hex 2-to-1 Data Selector/Multiplexer	24-DIP		—
74857	TTL-Logic		28-MP		—
7486	CMOS/TTL	Quad 2-Input EX-OR Gate	14-DIP		—
7488	Logic		20-MP		—
7486/2	TTL-Logic	Quad 2-Input EX-OR Gate	14-DIP		—
7486/3	TTL-Logic	Quad 2-Input EX-OR Gate	14-DIP		—
74861	CMOS/TTL	10-Bit Bus Transceiver, non inverting	24-DIP		—
74861	Logic				—
74862	CMOS/TTL	10-Bit Bus Transceiver, inverting	24-DIP		—
74862	Logic				—
74863	CMOS/TTL	9-Bit Bus Transceiver, non inverting	24-DIP		—
74863	Logic				—
74864	CMOS/TTL	9-Bit Bus Transceiver, inverting	24-DIP		—
74864	Logic				—
74866	TTL-Logic	8-Bit Comparator with Input/Output	40-DIP		—
74866	TTL-Logic	Register	28-MP		—
74867	TTL-Logic	Sync. Binary 8-Bit Up/Down Counter	24-DIP		—
74867	TTL-Logic	with Preset and Synchronous Clear	28-MP		—
74869	TTL-Logic	Sync. Binary 8-Bit Up/Down Counter	24-DIP		—
74869	TTL-Logic	with Preset and Asynchronous Clear	28-MP		—
7487	TTL-Logic	4-Bit Complementer	14-DIP		—
74870	TTL-Logic	Dual 16-Word x 4-Bit Register Files	24-DIP		—
74870	TTL-Logic		28-MP		—
74871	TTL-Logic	Dual 16-Word x 4-Bit Register Files	28-DIP		—
74871	TTL-Logic		28-MP		—
74873	TTL-Logic	Dual 4-Bit non inverting D-Latch	24-DIP		—
74873	TTL-Logic		28-MP		—
74874	TTL-Logic	Dual 4-Bit D-Register, non inverting	24-DIP		—
74874	TTL-Logic		28-MP		—
74876	TTL-Logic	Dual 4-Bit D-Register, inverting	24 DIP		—
74876	TTL-Logic		28-MP		—
74877	TTL-Logic	Universal Bi-Directional 8-Bit Port	24-DIP		—
74877	TTL-Logic	Controller	28-MP		—
74878	TTL-Logic	Dual 4-Bit D-Register, non inverting	24-DIP		—
74878	TTL-Logic		28-MP		—
74879	TTL-Logic	Dual 4-Bit D-Register, inverting	24-DIP		—
74879	TTL-Logic		28-MP		—
7488	TTL-Logic	32x8-Bit Read Only Memory (ROM)	16-DIP		—
74880	TTL-Logic	Dual 4-Bit D-Latch, inverting	24-DIP		—
74880	TTL-Logic		28-MP		—
74881	CMOS/TTL	4-Bit Arithmetic/Logic Unit, Function	24-DIP		—
74881	Logic	Generator			—
74882	TTL-Logic	32-Bit Carry Unit	24-DIP		—
74882	TTL-Logic		28-MP		—
74885	TTL-Logic	8-Bit Comparator, cascadable	24-DIP		—
74885	TTL-Logic		28-MP		—
7489	CMOS/TTL	16x4-Bit RAM	16-DIP		—
748960	TTL-Logic	Octal Bi-Directional Future Bus	28-DIP		—
748960	TTL-Logic	Transceiver with Latch, inverting	28-MP		—
748961	TTL-Logic	Octal Bi-Directional Future Bus	28-DIP		—
748961	TTL-Logic	Transceiver with Latch, non inverting	28-MP		—
74899	CMOS/TTL	9-Bit Bus Transceiver with Parity	28-MP		—
74899	Logic	Gen. a. Transparent Latch, non inver.			—
7490	Logic	Asynchronous Decimal Up Counter	14-DIP		—
749014	CMOS-Logic	Nine Buffer/Driver with Schmitt	20-DIP		—
749014	CMOS-Logic	Trigger Inputs, inverting			—
749015	CMOS-Logic	Nine Buffer/Driver with Schmitt	20-DIP		—
749015	CMOS-Logic	Trigger Inputs, non Inverting			—
7491	CMOS/TTL	8-Bit Serial Shift Register	14-DIP		—

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7491	Logic				—
7491/2	TTL-Logic	8-Bit Serial Shift Register	14-DIP		—
749114	CMOS-Logic	Nine Buffer/Driver with Schmitt	20-DIP		—
749114	CMOS-Logic	Trigger Inputs, inverting			—
749115	CMOS-Logic	Nine Buffer/Driver with Schmitt	20-DIP		—
749115	CMOS-Logic	Trigger Inputs, non inverting			—
7492	CMOS/TTL	Frequency Divider/Counter 12:1 (2:1	14-DIP		—
7492	Logic	and 8:1)			—
7493	CMOS/TTL	Asynchronous Binary 4-Bit Up Counter	14-DIP		—
7493	Logic				—
7493/2	TTL-Logic	Asynchronous Binary 4-Bit Up Counter	14-DIP		—
7494	TTL-Logic	4-Bit Shift Register with parallel	18-DIP		—
7494	TTL-Logic	NOR-Inputs, serial Output and Clear			—
74940	TTL-Logic	8-Bit Line Driver, inverting	20-DIP		—
74941	TTL-Logic	Octal Bus Line Driver, non inverting	20-DIP		—
7495	CMOS/TTL	4-Bit Shift Register with parallel	14-DIP		—
7495	Logic	Input/Output, right/left shifting			—
7495/2	TTL-Logic	4-Bit Shift Register with parallel	14-DIP		—
7495/2	TTL-Logic	Input/Output, right/left shifting			—
74952	TTL-Logic	8-Bit Shift Register with parallel	18-DIP		—
74952	TTL-Logic	Input/Output and Input/Output Latch			—
7496	TTL-Logic	5-Bit Shift Register with parallel	18-DIP		—
7496	TTL-Logic	Inputs/Outputs	20-MP		—
74962	TTL-Logic	8-Bit Shift Register with parallel	18-DIP		—
74962	TTL-Logic	Input/Output and Input/Output Latch			—
74963	TTL-Logic	8-Bit Multifunction Shift Register	20-DIP		—
74963	TTL-Logic	with parallel Input/Output	20-MP		—
74964	TTL-Logic	6-Bit Multifunction Shift Register	20-DIP		—
74964	TTL-Logic	with parallel Input/Output	20-MP		—
74968	TTL-Logic	Controller for 1 MBit Dynamic RAMs	52-MP		—
7497	TTL-Logic	Synchronous Programmable 6-Bit Binary	18-DIP		—
7497	TTL-Logic	Frequency Divider			—
7496	TTL-Logic	Quad 2-to-1 Data Selector/Multiplexer	18-DIP		—
7498	TTL-Logic	with Register			—
7499	TTL-Logic	4-Bit Shift Register with parallel	16-DIP		—
7499	TTL-Logic	Input/Output, right/left shifting			—
74990	TTL-Logic	8-Bit Transparent D-Latch with Read	20-DIP		—
74990	TTL-Logic	Back, non inverting	20-MP		—
74991	TTL-Logic	8-Bit Transparant D-Latch with Read	20-DIP		—
74991	TTL-Logic	Back, inverting	20-MP		—
74992	TTL-Logic	9-Bit Transparant D-Latch with Read	24-DIP		—
74992	TTL-Logic	Back, non inverting	28-MP		—
74993	TTL-Logic	9-Bit Transparent D-Latch with Read	24-DIP		—
74993	TTL-Logic	Back, inverting	28-MP		—
74994	TTL-Logic	10-Bit Transparent D-Latch with Read	24-DIP		—
74994	TTL-Logic	Back, non inverting	28-MP		—
74995	TTL-Logic	10-Bit Transparent D-Latch with Read	24-DIP		—
74995	TTL-Logic	Back, inverting	28-MP		—
74996	TTL-Logic	8-Bit D-Latch with Read Back,	24-DIP		—
74996	TTL-Logic	inverting/non inverting	28-MP		—
74T2	Si-N	=73T2: B>75	43g	Tho	(BD139, BD230, BD379, 2SC3252,++)
75	Si-P	=BFQ75 (Typ-Code/Stempel/marking)	51		→BFQ75
75(s,p)	Si-Di	=BAS70-05 (Typ-Code/Stempel/marking)	35		→BAS70-05
75Y	Z-Di	=BZV49/C75 (Typ-Code/Stempel/marking)	39		→BZV49/C75
78	Si-P	=BFQ76 (Typ-Code/Stempel/marking)	51		→BFQ76
76(s,p)	Si-Di	=BAS70-06 (Typ-Code/Stempel/marking)	35		→BAS70-06
77(s)	Si-Di	=BAS70-07 (Typ-Code/Stempel/marking)	44		→BAS70-07
779	Si-P	=S779T (Typ-Code/Stempel/marking)	35		→S779T
76	Si-P	=MMBT4258 (Typ-Code/Stempel/marking)	35		→MMBT4258
7A	C-Di	=MA374 (Typ-Code/Stempel/marking)	71(1,7mm)		→MA374
7A	Si-N	=MMBR901 (Typ-Code/Stempel/marking)	35		→MMBR901
7A	Si-P+R	=UN2121 (Typ-Code/Stempel/marking)	35		→UN2121
7AO	N-FET	=KTK136-O (Typ-Code/Stempel/marking)	35		→KTK136
7AY	N-FET	=KTK136-Y (Typ-Code/Stempel/marking)	35		→KTK136
7B	Si-N	=MMBR920 (Typ-Code/Stempel/marking)	35		→MMBR920
7B	Si-P+R	=UN2122 (Typ-Code/Stempel/marking)	35		→UN2122

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7BO	MOS-N-FET-d	=KTQ 127-O (Typ-Code/Stempel/marking)	44		→KTQ127-O
7BY	MOS-N-FET-d	=KTQ 127-Y (Typ-Code/Stempel/marking)	44		→KTQ127-Y
7C	C-Di	=MA376 (Typ-Code/Stempel/marking)	71(1,7mm)		→MA376
7C	Si-N	=MMBR930 (Typ-Code/Stempel/marking)	35		→MMBR930
7C	Si-P+R	=UN2123(Typ-Code/Stempel/marking)	35		→UN2123
7C	Si-N	=YTS 4123 (Typ-Code/Stempel/marking)	35		→YTS 4123
7D	Si-Di	=HD4A(Typ Code/Stempel/marking)	35		→HD4A
7D	C-Di	=MA377 (Typ-Code/Stempel/marking)	71(1,7mm)		→MA377
7D	Si-N	=MMBR931 (Typ-Code/Stempel/marking)	35		→MMBR931
7D	Si-P+R	=UN2124 (Typ-Code/Stempel/marking)	35		→UN2124
7E	Si-N	=FMMT-A42R (Typ-Code/Stempel/marking)	35		→FMMT-A42R
7E	Si-N	=MMBR2060 (Typ-Code/Stempel/marking)	35		→MMBR2060
7E	Si-N	=YTS 2221 (Typ-Code/Stempel/marking)	35		→YTS 2221
7F	Si-P	=MMBR4957 (Typ-Code/Stempel/marking)	35		→MMBR4957
7F	Si-N	=XN6534 (Typ-Code/Stempel/marking)	46		→XN6534
7F	Si-N	=XP6534 (Typ-Code/Stempel/marking)	46(2mm)		→XP 6534
7F	Si-N	=YTS 2221 A (Typ-Code/Stempel/marking)	35		→YTS2221A
7G	Si-N	=MMBR 5031 (Typ-Code/Stempel/marking)	35		→MMBR5031
7H	Si-N	=KST 5179 (Typ-Code/Stempel/marking)	35		→KST 5179
7H	Si-N	=MMBR 5179 (Typ-Code/Stempel/marking)	35		→MMBR5179
7H	Si-N	=XN6537 (Typ-Code/Stempel/marking)	46		→XN6537
71	Si-P+R	=UN212X (Typ-Code/Stempel/marking)	35		→UN212X
71	Si-N	=YTS 4400 (Typ-Code/Stempel/marking)	35		→YTS 4400
7K	C-Di	=MA357 (Typ-Code/Stempel/marking)	71(1,7mm)		→MA357
7K	Si-N	=MMBR2857 (Typ-Code/Stempel/marking)	35		→MMBR2857
7K	Si-P+R	=XN1112 (Typ-Code/Stempel/marking)	45		→XN1112
7K	Si-P+R	=XP1112 (Typ-Code/Stempel/marking)	45(2mm)		→XP 1112
7L	Si-P+R	=XN1113 (Typ-Code/Stempel/marking)	45		→XN 1113
7L	Si-P+R	=XP 1113 (Typ-Code/Stempel/marking)	45(2mm)		→XP 1113
7M	Si-P+R	=XN1115 (Typ-Code/Stempel/marking)	45		→XN1115
7M	Si-P+R	=XP 1115 (Typ-Code/Stempel/marking)	45(2mm)		→XP 1115
7N	C-Di	=MA392 (Typ-Code/Stempel/marking)	71(1,7mm)		→MA392
7N	Si-P+R	=XN1116 (Typ-Code/Stempel/marking)	45		→XN1116
7N	Si-P+R	=XP 1116 (Typ-Code/Stempel/marking)	45(2mm)		→XP 1116
7O	Si-P	=2SA1621-O (Typ-Code/Stempel/marking)	35		→2SA1621
7O	Si-P+R	=XN111F (Typ-Code/Stempel/marking)	45		→XN111F
7O	Si-P+R	=XP 111F (Typ-Code/Stempel/marking)	45(2mm)		→XP 111F
7P	Si-N	=BCW66RF (Typ-Code/Stempel/marking)	35		→BCW66RF
7P	C-Di	=MA393 (Typ-Code/Stempel/marking)	71(1,7mm)		→MA393
7P	Si-N	=MMBR911 (Typ-Code/Stempel/marking)	35		→MMBR911
7P	Si-P+R	=XN1119 (Typ-Code/Stempel/marking)	45		→XN1119
7P	Si-P+R	=XP 1119 (Typ-Code/Stempel/marking)	45(2mm)		→XP 1119
7Q	Si-P+R	=XN 1114 (Typ-Code/Stempel/marking)	45		→XN1114
7Q	Si-P+R	=XP 1114 (Typ-Code/Stempel/marking)	45(2mm)		→XP1114
7R	Si-P	=MMBR536 (Typ-Code/Stempel/marking)	35		→MMBR536
7R	Si-P	=XN2401 (Typ-Code/Stempel/marking)	45		→XN2401
7R	Si-P	=XP 2401 (Typ-Code/Stempel/marking)	45(2mm)		→XP 2401
7S	C-Di	=MA391 (Typ-Code/Stempel/marking)	71(1,7mm)		→MA391
7S	Si-P/N	=XN1601 (Typ-Code/Stempel/marking)	45		→XN1601
7S	Si-P/N	=XP1601 (Typ-Code/Stempel/marking)	45(2mm)		→XP 1601
7T	Si-N/P+R	=XN4312 (Typ-Code/Stempel/marking)	46		→XN4312
7T	Si-N/P+R	=XP4312 (Typ-Code/Stempel/marking)	46(2mm)		→XP4312
7U	Si-N/P+R	=XN4316 (Typ-Code/Stempel/marking)	46		→XN4316
7U	Si-N/P+R	=XP4316 (Typ-Code/Stempel/marking)	46(2mm)		→XP4316
7V	Si-N/P+R	=XN4322 (Typ-Code/Stempel/marking)	46		→XN4322
7W	Si-P	=XN6435 (Typ-Code/Stempel/marking)	46		→XN6435
7W	Si-P	=XP6435 (Typ-Code/Stempel/marking)	46(2mm)		→XP6435
7X	Si-N	=MMBR571 (Typ-Code/Stempel/marking)	35		→MMBR571
7X	Si-N/P+R	=XN4311 (Typ-Code/Stempel/marking)	46		→XN4311
7X	Si-N/P+R	=XP4311 (Typ-Code/Stempel/marking)	46(2mm)		→XP4311
7Y	Si-P	=2SA1621-Y (Typ-Code/Stempel/marking)	35		→2SA1621
7Y	Si-N	=MMBR941 (Typ-Code/Stempel/marking)	35		→MMBR941
7Y	Si-P+R	=UN212Y (Typ-Code/Stempel/marking)	35		→UN212Y
7Y5	Z-Di	=BZV 49/C7V5(Typ-Code/Stempel/marking)	39		→BZV49/C7V5
7Z	Si-N+R	=XN6211 (Typ-Code/Stempel/marking)	46		→XN6211
7Z	Si-N+R	=XP6211 (Typ-Code/Stempel/marking)	46(2mm)		→XP6211

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8		8			
8	C-Di	=HVU 308 (Typ-Code/Stempel/marking)	71(1,7mm)		→HVU308
8.2B	Z-Di	=HZF 8.2BP (Typ-Code/Stempel/marking)	71(5mm)		→HZF 8 2BP
8.2C	Z-Di	=HZF 8.2CP (Typ-Code/Stempel/marking)	71(5mm)		→HZF 8 2CP
8003 BB8	Si-N	=BF 337			→BF 337
801	Si-Di	=FC 801 (Typ-Code/Stempel/marking)	48		→FC 801
802	Si-Di	=FC 802 (Typ-Code/Stempel/marking)	46		→FC 802
803	Si-Di	=FC 803 (Typ-Code/Stempel/marking)	48		→FC 803
804	Si-Di	=FC 804 (Typ Code/Stempel/marking)	45		→FC 804
805	Si-Di	=FC 805 (Typ-Code/Stempel/marking)	45		→FC 805
8050	Si-N	=SS 8050			→SS 8050
806	Si-Di	=FC 806 (Typ-Code/Stempel/marking)	45		→FC 806
809	Si-Di	=FC 809 (Typ-Code/Stempel/marking)	45		→FC 809
80C31...C782	CMOS-µC-IC	8-Bit Single Chip Microcontroller, I2C		Phi	—
81 A	Z-Di	=PMBZ 5250B (Typ-Code/Stempel/marking)	35		→PMBZ 5250B
81 B1	Z-Di	=PMBZ 5251 B (Typ-Code/Stempel/marking)	35		→PMBZ 5251B
81 C	Z-Di	=PMBZ 5252B (Typ-Code/Stempel/marking)	35		→PMBZ 5252B
81 D	Z-Di	=PMBZ 5253B(Typ-Code/Stempel/marking)	35		→PMBZ 5253B
81 E	Z-Di	=PMBZ 5254B(Typ-Code/Stempel/marking)	35		→PMBZ 5254B
81 F	Z-Di	=PMBZ 5255B(Typ-Code/Stempel/marking)	35		→PMBZ 5255B
81 G	Z-Di	=PMBZ 5256B(Typ-Code/Stempel/marking)	35		→PMBZ 5256B
81 H	Z-Di	=PMBZ 5257B(Typ-Code/Stempel/marking)	35		→PMBZ 5257B
82	Si-N	=BFQ 82 (Typ-Code/Stempel/marking)	51		→BFQ 82
83	Si-Di	=BAT 68 (Typ-Code/Stempel/marking)	35		→BAT 68
83C053	CMOS-µC-IC	TV Microcontr., 8192x8 Bitmask. ROM	42-DIP	Phi	—
83C054	CMOS-µC-IC	TV Microcontr., 16384x8 Bitmask. ROM	42-DIP	Phi	—
83C528..C654	CMOS-µC-IC	8-Bit Single Chip Microcontroller, I2C		Phi	—
83C528..C654	CMOS-µC-IC	TV, 8-Bit Microcontr., EPROM, I2C-Bus		Phi	—
84	Si-Di	=BAT 68-04 (Typ-Code/Stempel/marking)	35		→BAT 68-04
84C44..	CMOS-µC-IC	8 Bit, Volt. Synth. Tuning, OSD, I2C	42-SDIP	Phi	—
84C84..	CMOS-µC-IC	8 Bit, Volt. Synth. Tuning, OSD, I2C	42-SDIP	Phi	—
84C84..	CMOS-µC-IC	8 Bit, Volt. Synth. Tuning, OSD, I2C	42-SDIP	Phi	—
85	Si-Di	=BAT 68-05 (Typ-Code/Stempel/marking)	35		→BAT 68-05
8550	Si-P	=SS 8550			→SS 8550
86	Si-Di	=BAT 68-06 (Typ-Code/Stempel/marking)	35		→BAT 68-06
87(e)	Si-Di	=BAT 68-07 (Typ-Code/Stempel/marking)	44		→BAT 68-07
879	Si-P	=S 879 T (Typ-Code/Stempel/marking)	35		→S 879T
87 C054	CMOS-µC-IC	TV Microcontr, 16384x8 Bit EPROM, I2C	42-DIP	Phi	—
887	MOS-N-FET-d	=S 687 (Typ-Code/Stempel/marking)	44		→S 687
896	Se-Di	→AEG 898	31e	Aeg	—
897	Si-N	=S 897T (Typ-Code/Stempel/marking)	44		→S 897T
8A	Z-IC	=HA 178L02UA(Typ-Code/Stempel/marking)	39		→HA 178L02UA
8A	Si-N+R	=MUN 2211 (Typ-Code/Stempel/marking)	35		→MUN2211
8P	Si-N+R	=MUN 5211 (Typ-Code/Stempel/marking)	35(2mm)		→MUN5211
8P	Z-Di	=PMBZ 5226B (Typ-Code/Stempel/marking)	35		→PMBZ 5226B
8P	Si-N+R	=UN 2211 (Typ-Code/Stempel/marking)	35		→UN2211
8P	Si-N+R	=UN 5211 (Typ-Code/Stempel/marking)	35(2mm)		→UN5211
8P	Si-N+R	=UN 9211 (Typ-Code/Stempel/marking)	35(1,6mm)		→UN9211
8B	Z-IC	=HA 178L05UA(Typ-Code/Stempel/marking)	39		→HA 178L05UA
8B	Si-N+R	=MUN 2212 (Typ-Code/Stempel/marking)	35		→MUN2212
8B	Si-N+R	=MUN 5212 (Typ-Code/Stempel/marking)	35(2mm)		→MUN5212
8B	Z-Di	=PMBZ 5227B (Typ-Code/Stempel/marking)	35		→PMBZ 5227B
8B	Si-N+R	=UN 2212 (Typ-Code/Stempel/marking)	35		→UN2212
8B	Si-N+R	=UN 5212 (Typ Code/Stempel/marking)	35(2mm)		→UN5212
8B	Si-N+R	=UN 9212 (Typ-Code/Stempel/marking)	35(1,6mm)		→UN9212
8C	Z-IC	=HA 178L56UA(Typ-Code/Stempel/marking)	39		→HA 178L56UA
8C	Si-N+R	=MUN 2213 (Typ-Code/Stempel/marking)	35		→MUN2213
8C	Si-N+R	=MUN 5213 (Typ Code/Stempel/marking)	35(2mm)		→MUN5213
8C	Z-Di	=PMBZ 5228B (Typ-Code/Stempel/marking)	35		→PMBZ 5228B
8C	Si-N+R	=UN 2213 (Typ Code/Stempel/marking)	35		→UN2213
8C	Si-N+R	=UN 5213 (Typ-Code/Stempel/marking)	35(2mm)		→UN5213
8C	Si-N+R	=UN 9213 (Typ-Code/Stempel/marking)	35(1,6mm)		→UN9213
8D	Z-IC	=HA 178L06UA(Typ-Code/Stempel/marking)	39		→HA 178L06UA
8D	Si-N+R	=MUN 2214 (Typ-Code/Stempel/marking)	35		→MUN2214
8D	Si-N+R	=MUN 5214 (Typ-Code/Stempel/marking)	35(2mm)		→MUN5214

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8D	Z-Di	=PMBZ 5229B (Typ-Code/Stempel/marking)	35		→PMBZ 5229B
8D	Si-N+R	=UN 2214 (Typ-Code/Stempel/marking)	35		→UN2214
8D	Si-N+R	=UN 5214 (Typ-Code/Stempel/marking)	35(2mm)		→UN5214
8D	Si-N+R	=UN 9214 (Typ-Code/Stempel/marking)	35(1,6mm)		→UN9214
8E	Si-P	=FMMT-A92R (Typ-Code/Stempel/marking)	35		→FMMT-A92R
8E	Z-IC	=HA 178L08UA (Typ-Code/Stempel/marking)	39		→HA 178L08UA
8E	Si-N+R	=MUN 2215 (Typ-Code/Stempel/marking)	35		→MUN2215
8E	Si-N+R	=MUN 5215 (Typ-Code/Stempel/marking)	35(2mm)		→MUN5215
8E	Z-Di	=PMBZ 5230B (Typ-Code/Stempel/marking)	35		→PMBZ 5230B
8E	Si-N+R	=UN 2215 (Typ-Code/Stempel/marking)	35		→UN2215
8E	Si-N+R	=UN 5215 (Typ-Code/Stempel/marking)	35(2mm)		→UN5215
8E	Si-N+R	=UN 9215 (Typ-Code/Stempel/marking)	35(1,6mm)		→UN9215
8F	Z-IC	=HA 178L09UA (Typ-Code/Stempel/marking)	39		→HA 178L09UA
8F	Si-N+R	=MUN 2216 (Typ-Code/Stempel/marking)	35		→MUN2216
8F	Si-N+R	=MUN 5216 (Typ-Code/Stempel/marking)	35(2mm)		→MUN5218
8F	Z-Di	=PMBZ 5231B (Typ-Code/Stempel/marking)	35		→PMBZ 5231B
8F	Si-N+R	=UN 2216 (Typ-Code/Stempel/marking)	35		→UN2218
8F	Si-N+R	=UN 5216 (Typ-Code/Stempel/marking)	35(2mm)		→UN5218
8F	Si-N+R	=UN 9216 (Typ-Code/Stempel/marking)	35(1,6mm)		→UN9218
8G	Z-IC	=HA 178L10UA (Typ-Code/Stempel/marking)	39		→HA 178L10UA
8G	Si-N+R	=MUN 2230 (Typ-Code/Stempel/marking)	35		→MUN2230
8G	Si-N+R	=MUN 5230 (Typ-Code/Stempel/marking)	35(2mm)		→MUN5230
8G	Z-Di	=PMBZ 5232B (Typ Code/Stempel/marking)	35		→PMBZ232B
8H	Z-IC	=HA 178L12UA (Typ-Code/Stempel/marking)	39		→HA178L12UA
8H	Si-N+R	=MUN 2231 (Typ-Code/Stempel/marking)	35		→MUN2231
8H	Si-N+R	=MUN 5231 (Typ-Code/Stempel/marking)	35(2mm)		→MUN5231
8H	Z-Di	=PMBZ 5233B (Typ-Code/Stempel/marking)	35		→PMBZ 5233B
8H	SiI-N+R	=UN 2217 (Typ-Code/Stempel/marking)	35		→UN2217
8H	Si-N+R	=UN 5217 (Typ-Code/Stempel/marking)	35(2mm)		→UN5217
6H	Si-N+R	=UN 9217 (Typ-Code/Stempel/marking)	35(1,6mm)		→UN9217
8I	Si-N+R	=UN 2216 (Typ-Code/Stempel/marking)	35		→UN2218
8I	Si-N+R	=UN 5218 (Typ-Code/Stempel/marking)	35(2mm)		→UN5218
8I	Si-N+R	=UN 9218 (Typ-Code/Stempel/marking)	35(1,6mm)		→UN9218
8J	Z-IC	=HA 178L15UA (Typ-Code/Stempel/marking)	39		→HA 178L15UA
8J	Si-N+R	=MUN 2232 (Typ-Code/Stempel/marking)	35		→MUN2232
8J	Si-N+R	=MUN 5232 (Typ-Code/Stempel/marking)	35(2mm)		→MUN5232
8J	Z-Di	=PMBZ 5234B (Typ-Code/Stempel/marking)	35		→PMBZ 5234B
8K	Si-N+R	=MUN 2233 (Typ Code/Stempel/marking)	35		→MUN2233
8K	Si-N+R	=MUN 5233 (Typ-Code/Stempel/marking)	35(2mm)		→MUN5233
8K	Z-Di	=PMBZ 5235B (Typ-Code/Stempel/marking)	35		→PMBZ5235B
8K	Si-N+R	=UN 2219 (Typ Code/Stempel/marking)	35		→UN2219
8K	Si-N+R	=UN 5219 (Typ-Code/Stempel/marking)	35(2mm)		→UN5219
8K	Si-N+R	=UN 9219 (Typ-Code/Stempel/marking)	35(1,6mm)		→UN9219
8L	Si-N+R	=MUN 2234 (Typ Code/Stempel/marking)	35		→MUN2234
8L	Si-N+R	=MUN 5234 (Typ-Code/Stempel/marking)	35(2mm)		→MUN5234
8L	Z-Di	=PMBZ 5236B (Typ-Code/Stempel/marking)	35		→PMBZ 5235B
8L	Si-N+R	=UN 2210 (Typ-Code/Stempel/marking)	35		→UN2210
8L	Si-N+R	=UN 5210 (Typ Code/Stempel/marking)	35(2mm)		→UN5210
8L	Si-N+R	=UN 9210 (Typ-Code/Stempel/marking)	35(1,6mm)		→UN9210
8M	Z-Di	=PMBZ 5237B (Typ-Code/Stempel/marking)	35		→PMBZ 5237B
8M	Si-N+R	=UN 221D (Typ-Code/Stempel/marking)	35		→UN221D
8M	Si-N+R	=UN 521D (Typ-Code/Stempel/marking)	35(2mm)		→UN521D
8M	Si-N+R	=UN 921D (Typ-Code/Stempel/marking)	35(1,6mm)		→UN921D
6N	Z-Di	=PMBZ 5238B (Typ Code/Stempel/marking)	35		→PMBZ 5238B
8N	Si-N+R	=UN 221E (Typ-Code/Stempel/marking)	35		→UN221E
8N	Si-N+R	=UN 521E (Typ-Code/Stempel/marking)	35(2mm)		→UN521E
8N	Si-N+R	=UN 921E (Typ-Code/Stempel/marking)	35(1,6mm)		→UN921E
8O	Si-N+R	=UN 221F (Typ-Code/Stempel/marking)	35		→UN221F
8O	Si-N+R	=UN 521F (Typ-Code/Stempel/marking)	35(2mm)		→UN521F
6O	Si-N+R	=UN 921F (Typ-Code/Stempel/marking)	35(1,6mm)		→UN921F
8P	Z-Di	=PMBZ 5239B (Typ-Code/Stempel/marking)	35		→PMBZ5239B
8P	Si-N+R	=UN 221K (Typ Code/Stempel/marking)	35		→UN221K
8P	Si-N+R	=UN 521K (Typ-Code/Stempel/marking)	35(2mm)		→UN521K
8P	Si-N+R	=UN 921K (Typ-Code/Stempel/marking)	35(1,6mm)		→UN921K
8P1M	50Hz-Thy	100V, 8A(Tc=90°C), Igt/Ih<15/<10mA	17e	Nec	TIC122.., TIC126.., T7,5N.., ++
8P2M	50Hz-Thy	=8P1M: 200V	17e		TIC122.., TIC126.., T7,5N.., ++

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8P4J(Z)	50Hz-Thy	400V, 8A(Tc=75°C), Igt/Ih <10/=6mA	30e	Nec	—
8Q	Z-Di	=PMBZ 5240B (Typ-Code/Stempel/marking)	35		→PMBZ 5240B
8Q	Si-N+R	=UN221L (Typ-Code/Stempel/marking)	35		→UN221L
8Q	Si-N+R	=UN521L (Typ-Code/Stempel/marking)	35(2mm)		→UN521L
8Q	Si-N+R	=UN921L (Typ-Code/Stempel/marking)	35(1,6mm)		→UN921L
8R	Z-Di	=PMBZ 5241B (Typ-Code/Stempel/marking)	35		→PMBZ 5241B
8R	Si-N+R	=XN 4212 (Typ-Code/Stempel/marking)	46		→XN4212
8R	Si-N+R	=XP 4212 (Typ-Code/Stempel/marking)	46(2mm)		→XP 4212
8S	Z-Di	=PMBZ 5242B (Typ-Code/Stempel/marking)	35		→PMBZ 5242B
8S	Si-N+R	=UN 5201 (Typ-Code/Stempel/marking)	35(2mm)		→UN5201
8S	Si-N+R	=XN 4213 (Typ-Code/Stempel/marking)	46		→XN4213
8S	Si-N+R	=XP 4213 (Typ-Code/Stempel/marking)	46(2mm)		→XP 4213
8T	Z-Di	=PMBZ 5243B (Typ-Code/Stempel/marking)	35		→PMBZ 5243B
8T	Si-N+R	=XN 4215 (Typ-Code/Stempel/marking)	46		→XN4215
8T	Si-N+R	=XP 4215 (Typ-Code/Stempel/marking)	46(2mm)		→XP 4215
8U	Z-Di	=PMBZ 5244B (Typ-Code/Stempel/marking)	35		→PMBZ 5244B
8U	Si-N+R	=XN 4216 (Typ-Code/Stempel/marking)	46		→XN4216
8U	Si-N+R	=XP 4216 (Typ-Code/Stempel/marking)	46(2mm)		→XP 4216
8V	Z-Di	=PMBZ 5245B (Typ-Code/Stempel/marking)	35		→PMBZ 52445B
8V	Si-N+R	=XN 6212 (Typ-Code/Stempel/marking)	46		→XN6212
8V	Si-N+R	=XP 6212 (Typ-Code/Stempel/marking)	46(2mm)		→XP 6212
8W	Z-Di	=PMBZ 5246B (Typ-Code/Stempel/marking)	35		→PMBZ 52446B
8W	Si-N+R	=XN 6213 (Typ-Code/Stempel/marking)	46		→XN6213
8W	Si-N+R	=XP 6213 (Typ-Code/Stempel/marking)	46(2mm)		→XP 6213
8X	Z-Di	=PMBZ 5247B (Typ-Code/Stempel/marking)	35		→PMBZ 52447B
8X	Si-N+R	=XN 6215 (Typ-Code/Stempel/marking)	46		→XN6215
8X	Si-N+R	=XP 6215 (Typ-Code/Stempel/marking)	46(2mm)		→XP 6215
8Y	Z-Di	=PMBZ 5248B (Typ-Code/Stempel/marking)	35		→PMBZ 52448B
8Y	Si-N+R	=XN 6216 (Typ-Code/Stempel/marking)	46		→XN6216
8Y	Si-N+R	=XP 6216 (Typ-Code/Stempel/marking)	46(2mm)		→XP 6216
8Y2	Z-Di	=BZV 49/C8V2 (Typ-Code/Stempel/marking)	39		→BZV 49/C8V2
8Z	Z-Di	=PMBZ 5249B (Typ-Code/Stempel/marking)	35		→PMBZ 524469
8Z	Si-N+R	=XN 4210 (Typ-Code/Stempel/marking)	46		→XN4210
8Z	Si-N+R	=XP 4210 (Typ-Code/Stempel/marking)	46(2mm)		→XP 4210
9		**9**			
9	Si-Di	=HSU 88 (Typ-Code/Stempel/marking)	71(1,7mm)		→HSU 88
9.1B	Z-Di	=HZF 9.1BP (Typ-Code/Stempel/marking)	71(5mm)		→HZF91BP
9.1C	Z-Di	=HZF 9.1CP (Typ-Code/Stempel/marking)	71(5mm)		→HZF91CP
9.1C	Z-Di	=HZF 9.1CP (Typ-Code/Stempel/marking)	71(5mm)		→HZF91CP
9003	Si-N	→CS 9003	7e		—
9010	Si-N	→CS 9010	7e		—
9011	Si-N	=SS 9011	7e		→SS 9011
9012(HH)	Si-P	=SS 9012	7e		→SS 9012
9013(HH)	Si-N	=SS 9013	7e		→SS 9013
9014	Si-N	=SS 9014	7e		→SS 9014
9015	Si-P	=SS 9015	7e		→SS 9015
9016	Si-N	=SS 9016	7e		→SS 9016
9017	Si-N	→CS 9017	7e		—
9018	Si-N	=SS 9018	7e		→SS 9018
9020	Si-P	→CS 9020	7e		—
9021	Si-N	→CS 9021	7e		—
9022	Si-N	→CS 9022	7e		—
903	Si-Di	=FC 903 (Typ-Code/Stempel/marking)	46		→FC903
90T2	Si-N	=2N1990: 0,2W	7c	Tho	BC639, 2N3700. 01, 2SD667, 2SD774, ++
91	N-FET	=2SK300-1 (Typ-Code/Stempel/marking)	35		→2SK300
92	N-FET	=2SK300-2 (Typ-Code/Stempel/marking)	35		→2SK300
92GE37A...C	Si-N	=2N6705..6707	30c	Gen	→2N6705..6707
92GE487	Si-N	=2N6711	30c	Gen	→2N6711
92GE488	Si-N	=2N6712	30c	Gen	→2N6712
92GE489	Si-N	=2N6713	30c	Gen	→2N6713
92GE77A...C	Si-P	=2N6708..6710	30c	Gen	→2N6708..6710
92GU01	Si-N	=2N6714	30e	Gen	→2N6714
92GU01A	Si-N	=2N6715	30e	Gen	→2N6715
92GU05	Si-N	=2N6716	30e	Gen	→2N6716
92GU06	Si-N	=2N6717	30e	Gen	→2N6717

ТИП	СТРУКТУРА	ХАРАКТЕРИСТИКИ	КОРПУС	ПРОИЗВОДИТЕЛЬ	АНАЛОГ
92GU10	Si-N	=2N6719	30e	Gen	→2N6719
92GU391	Si-N	=2N6733	30e	Gen	→2N6733
92GU392	Si-N	=2N6734	30e	Gen	→2N6734
92GU393	Si-N	=2N6735	30e	Gen	→2N6735
92GU45	Si-N	=2N6724	30e	Gen	→2N6724
92GU45A	Si-N	=2N6725	30e	Gen	→2N6725
92GU51	Si-P	=2N6726	30e	Gen	→2N6726
92GU51A	Si-P	=2N6727	30e	Gen	→2N6727
92GU55	Si-P	=2N6728	30e	Gen	→2N6728
92GU56	Si-P	=2N6729	30e	Gen	→2N6729
92PE37A	Si-N	Uni, 60/45V, ≈1A, 0,85W, >50MHz	30c	Nsc	(BD517, BD525, 2SD1281..1284,++)
92PE37B	Si-N	=92PE37A: 80/60V	30c		(BD519, BD527, 2SD1281..1284,++)
92PE37C	Si-N	=92PE37A: 100/80V	30c		(BD519, BD529, 2SD1281..1284,++)
92PE487	Si-N	Vid, 160/180V, ≈0,03A, 0,85W	30c	Nsc	(BF815, BF817, BF757..759,++)
92PE488	Si-N	=92PE487: 250/250V	30c		(BF815, BF617, BF757..759,++)
92PE489	Si-N	=92PE487: 300/300V	30c		(BF617, BF758..759, MPS-U10,++)
92PE77A	Si-P	Uni, 60/45V, ≈1A, 0,85W, >50MHz	30c	Nsc	(BD518, BD526, 2SB957..960,++)
92PE77B	Si-P	=92PE77A: 60/80V	30c		(BD520, BD528, 2SB957..960,++)
92PE77C	Si-P	=92PE77A: 100/80V	30c		(BD520, BD530, 2SB957..960,++)
92PU01	Si-N	Uni, 40/80V, 2A, 0,85W, >100MHz	30e	Nsc, Mic	(BD507, BD515, BD525, 2SD1801,++)
92PU01A	Si-N	=92PU01: 50/40V	30e		(BD509, BD515, BD525, 2SD1801,++)
92PU02	Si-N	Uni, -/40V, 0,8A, 0,85W, >150MHz	30e	Mic	(BD515, BD525, 2SD1074..75, 2SD1733++)
92PU05	Si-N	Uni, -/60V, 2A, 0,85W, >50MHz	30e	Nsc, Mic	(BD527, BD529, 2SC4135, 2SD1281..82++)
92PU06	Si-N	Uni, -/60V, 2A, 0,85W, >50MHz	30e	Nsc, Mic	(BD527, BD529, 2SC4135, 2SD1261..82++)
92PU07	Si-N	Uni, -/80V, 2A, 0,85W, >50MHz	30e	Nsc, Mic	(BD527, BD529, 2SC4135, 2SD1261..82++)
92PU10	Si-N	Vid, -/300V, 0,5A, 0,85W	30e	Nsc, Mic	(BF482, BF758..759, MPS-U10,++)
92PU100	Si-N	Uni, 100/80V, ≈1A, 0,85W, >50MHz	30e	Nsc	(BD529, 2SD1074..75, 2SD1281..84,++)
92PU200	Si-P	Uni, 100/80V, ≈1A, 0,85W, >50MHz	30e	Nsc	(BD530, 2SB844..845, 2SB957..960,++)
92PU36	Si-N	NF/Vid, 175/150V, ≈0,5A, 0,85W	30e	Nsc	(BF466..468, BF888..688, BF757..759+)
92PU36A	Si-N	=92PU36: 225/200V	30e		(BF467..466, BF967..668, BF757..759+)
92PU36B	Si-N	=92PU36: 275/250V	30e		(BF466, BF668, BF756..759,++)
92PU36C	Si-N	=92PU36: 325/300V	30e		(BF462, BF759)
92PU391	Si-N	Vid, 200/200V, 0,65W, >50MHz	30e	Nsc	(BF615, BF817, BF757..759, MPS-U10++)
92PU392	Si-N	=92PU391: 250/250V	30e	Nsc	(BF615, BF817, BF757..759, MPS-U10++)
92PU393	Si-N	=92PU391: 300/300V	30e	Nsc	(BF617, BF758..759, MPS-U10,++)
92PU45	Si-N-Darl	Uni, 50V, 2A, 0,85W, >100MHz, B>25000	30e	Nsc, Mic	—
92PU45A	Si-N-Darl	=92PU45: 80V	30e		—
92PU51	Si-P	Uni, 40/30V, 2A, 0,85W, >50MHz	30e	Nsc, Mic	(BD506, BD518, BD526, 2SB1201,++)
92PU51A	Si-P	=92PU51: 50/40V	30e		(BD510, BD516, BD526, 2SB1201,++)
92PU52	Si-P	Uni, -/40V, 0,8A, 0,85W, >150MHz	30e	Mic	(BD516, BD526, 2SB844..45, 2SB1181++)
92PU55	Si-P	Uni, -/60V, 2A, 0,85W, >50MHz	30e	Nsc, Mic	(BD528, BD530, 2SA1593, 2SB957..56++)
92PU56	Si-P	=92PU56: -/80V	30e	Nsc, Mic	(BD528, BD530, 2SA1593, 2SB957..56++)
92PU57	Si-P	=92PU56: -/100V	30e	Nsc, Mic	(BD530, 2SA1593, 2SB957..58,++)
92PU60	Si-P	Vid, -/300V, 0,5A, 0,85W, >50MHz	30e	Mic	(BF465, BF761..762, MPS-U60,++)
92PU95	Si-P-Darl	Uni, 40V, 2A, 0,85W, >50MHz, B>15000	30e	Mic	—
92V	Si-N	=BFP92A (Typ-Code/Stempel/marking)	44		→BFP92A
93	N-FET	=2SK300-3 (Typ-Code/Stempel/marking)	35		→2SK300
94	N-FET	=2SK300-4 (Typ-Code/Stempel/marking)	35		→2SK300
9400	Si-N	≈BC337			→BC337
9665	LIN-IC	=ULN2001A	16-DIP	Mot	MC1411, ULN2001A
9666	LIN-IC	=ULN2002A	16-DIP	Mot	MC1412, ULN2002A
9667	LIN-IC	=ULN2003A	16-DIP	Mot	MC1413, ULN2003A
9668	LIN-IC	=ULN2004A	16-DIP	Mot	MC1416, ULN2004A
97(p)	Si-N/P	=BCV85 (Typ-Code/Stempel/marking)	44		→BCV85
972	Se-Di	→AEG972	31a	Aeg	—
96(p)	Si-N/P	=BCV65B (Typ-Code/Stempel/marking)	44		→BCV85B
992	Se-Di	→AEG992	31a	Aeg	—
9A	Si-N+R	=UN2221 (Typ-Code/Stempel/marking)	35		→UN2221
9B	Z-IC	=HA179L05U (Typ-Code/Stempel/marking)	39		→HA179L05U
9B	Si-N+R	=UN2222 (Typ-Code/Stempel/marking)	35		→UN2222
9C	Si-N+R	=UN2223 (Typ-Code/Stempel/marking)	35		→UN2223
9D	Z-IC	=HA179L06U (Typ-Code/Stempel/marking)	39		→HA179L06U
9D	Si-N+R	=UN2224 (Typ-Code/Stempel/marking)	35		→UN2224
9E	Z-IC	=HA179L06U (Typ-Code/Stempel/marking)	39		→HA179L06U
9F	Z-IC	=HA179L09U (Typ-Code/Stempel/marking)	39		→HA179L09U
9F	Si-N	=XN1531 (Typ-Code/Stempel/marking)	45		→XN1531

ТИП	СТРУКТУРА	ХАРАКТЕРИСТИКИ	КОРПУС	ПРОИЗВОДИТЕЛЬ	АНАЛОГ
9G	Z-IC	=HA 179L10U (Typ-Code/Stempel/marking)	39		→HA 179L10U
9H	Z-IC	=HA 179L12U (Typ-Code/Stempel/marking)	39		→HA 179L12U
9H	Si-N+R	=XN 1214 (Typ-Code/Stempel/marking)	45		→XN 1214
9H	Si-N+R	=XP 1214 (Typ-Code/Stempel/marking)	45(2mm)		→XP 1214
9I	Si-N	=XN 2531 (Typ-Code/Stempel/marking)	45		→XN 2531
9J	Z-IC	=HA 179L15U (Typ-Code/Stempel/marking)	39		→HA 179L15U
9K	Si-N+R	=XN 1212 (Typ-Code/Stempel/marking)	45		→XN 1212
9K	Si-N+R	=XP 1212 (Typ-Code/Stempel/marking)	45(2mm)		→XP 1212
9L	Si-N+R	=XP 1213 (Typ-Code/Stempel/marking)	45(2mm)		→XP 1213
9M	Si-N+R	=XN 1215 (Typ-Code/Stempel/marking)	45		→XN 1215
9M	Si-N+R	=XP 1215 (Typ-Code/Stempel/marking)	45(2mm)		→XP 1215
9N	Si-N+R	=XN 1216 (Typ-Code/Stempel/marking)	45		→XN 1216
9N	Si-N+R	=XP 1216 (Typ-Code/Stempel/marking)	45(2mm)		→XP 1216
9O	Si-N+R	=XN 2211 (Typ-Code/Stempel/marking)	45		→XN 2211
9O	Si-N+R	=XP 2211 (Typ-Code/Stempel/marking)	45(2mm)		→XP 2211
9P	Si-N+R	=XN 1217 (Typ-Code/Stempel/marking)	45		→XN 1217
9P	Si-N+R	=XP 1217 (Typ-Code/Stempel/marking)	45(2mm)		→XP 1217
9Q	Si-N+R	=XN 2210 (Typ-Code/Stempel/marking)	45		→XN 2210
9Q	Si-N+R	=XP 2210 (Typ-Code/Stempel/marking)	45(2mm)		→XP 2210
9R	Si-N+R	=XN 2215 (Typ-Code/Stempel/marking)	45		→XN 2215
9R	Si-N+R	=XP 2215 (Typ-Code/Stempel/marking)	45(2mm)		→XP 2215
9S	Si-P+R	=XN 1111 (Typ-Code/Stempel/marking)	45		→XN 1111
9S	Si-P+R	=XP 1111 (Typ-Code/Stempel/marking)	45(2mm)		→XP 1111
9T	Si-N+R	=XN 1211 (Typ-Code/Stempel/marking)	45		→XN 1211
9T	Si-N+R	=XP 1211 (Typ-Code/Stempel/marking)	45(2mm)		→XP 1211
9U	Si-P+R	=XN 4111 (Typ-Code/Stempel/marking)	46		→XN 4111
9U	Si-P	=XP 4111 (Typ-Code/Stempel/marking)	46(2mm)		→XP 4111
9V	Si-N+R	=XN 4211 (Typ-Code/Stempel/marking)	46		→XN 4211
9V	Si-N+R	=XP 4211 (Typ-Code/Stempel/marking)	46(2mm)		→XP 4211
9W	Si-N/P	=XN 7651 (Typ-Code/Stempel/marking)	46		→XN 7651
9X	Si-P+R	=XN 111H (Typ-Code/Stempel/marking)	45		→XN 111H
9X	Si-P+R	=XP 111H (Typ-Code/Stempel/marking)	45(2mm)		→XP 111H
9Y	Si-N	=XN 6543 (Typ-Code/Stempel/marking)	46		→XN 6543
9Y1	Z-Di	=BZV 49/C9V1 (Typ-Code/Stempel/marking)	39		→BZV 49/C9V1
9Z	Si-N+N-FET	=XN 8081 (Typ-Code/Stempel/marking)	46		→XN 8081
9Z	Si-N+N-FET	=XP 8081 (Typ-Code/Stempel/marking)	46(2mm)		→XP 8081

СОЕДИНЕНИЕ ТРАНЗИСТОРОВ ПО СХЕМЕ ДАРЛИНГТОНА (СОСТАВНЫЕ ТРАНЗИСТОРЫ)

Схема A
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Схема B
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Схема C
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Схема D
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Схема E
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Схема F
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Схема G
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Схема H
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Схема I
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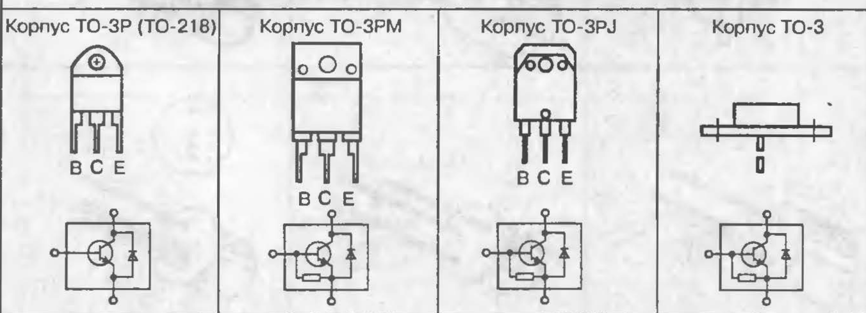
Схема J
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Схема M
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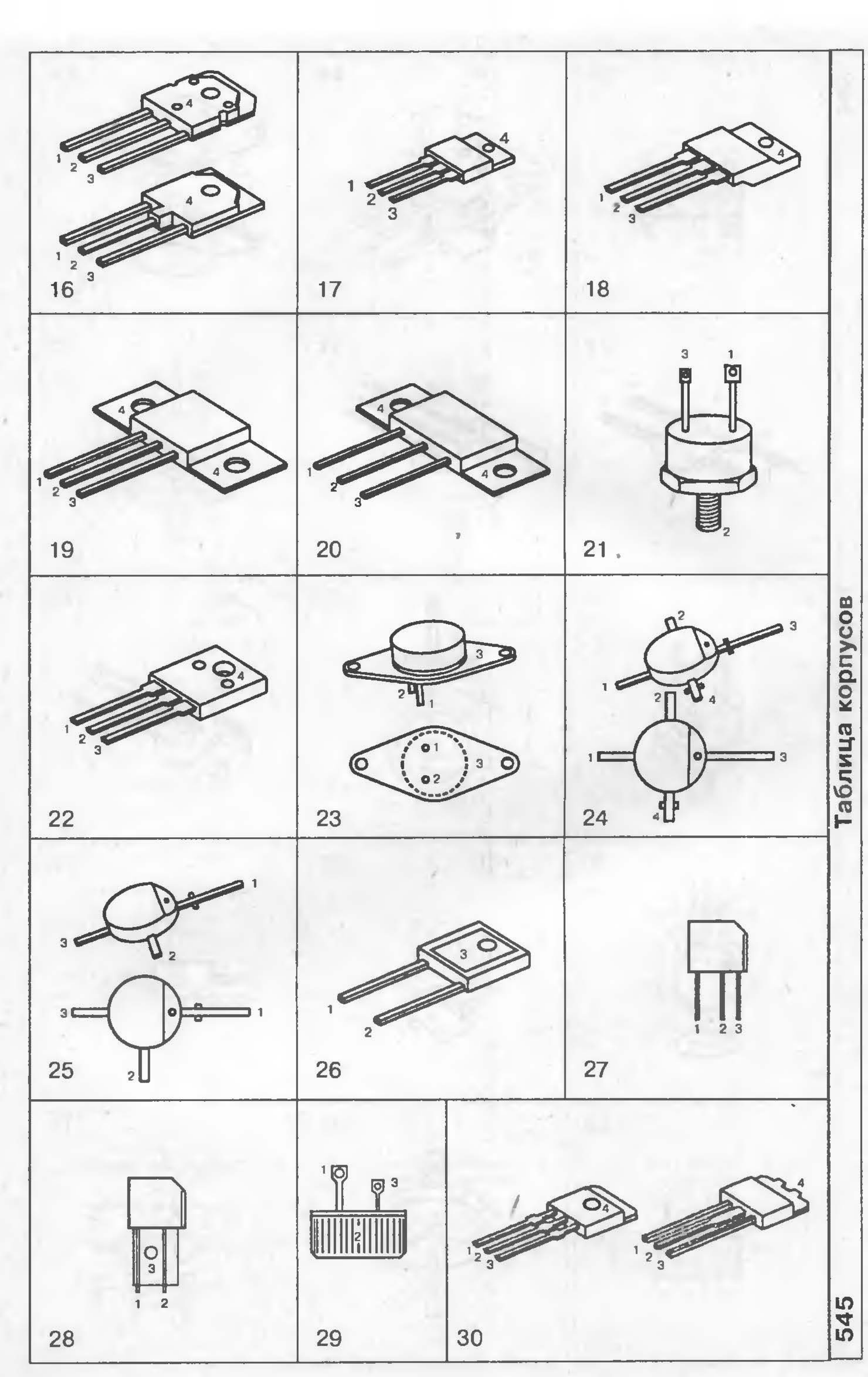
ТРАНЗИСТОРЫ ДЛЯ ВЫХОДНЫХ КАСКАДОВ СТРОЧНОЙ РАЗВЕРТКИ С ВСТРОЕННЫМИ КОМПОНЕНТАМИ

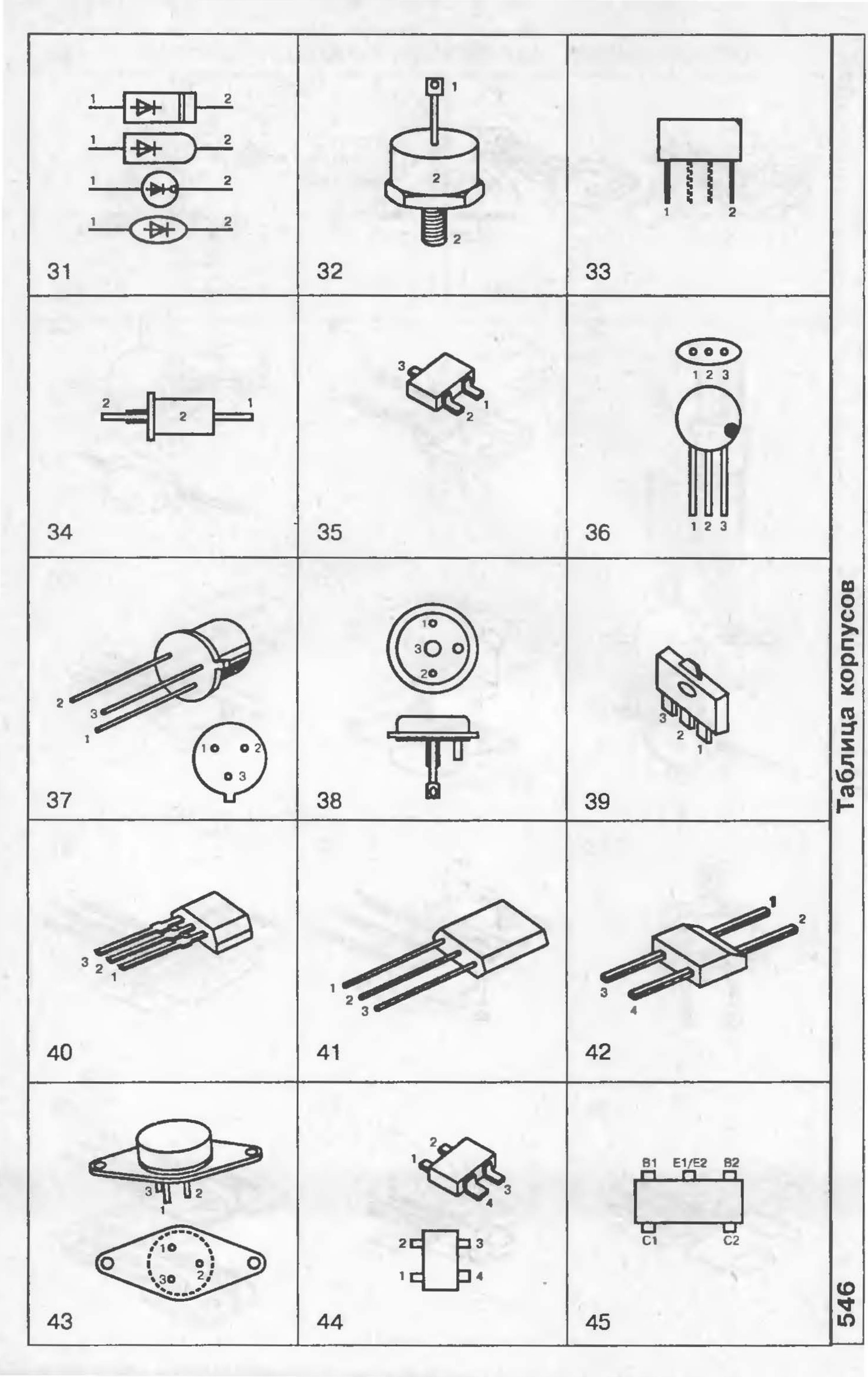


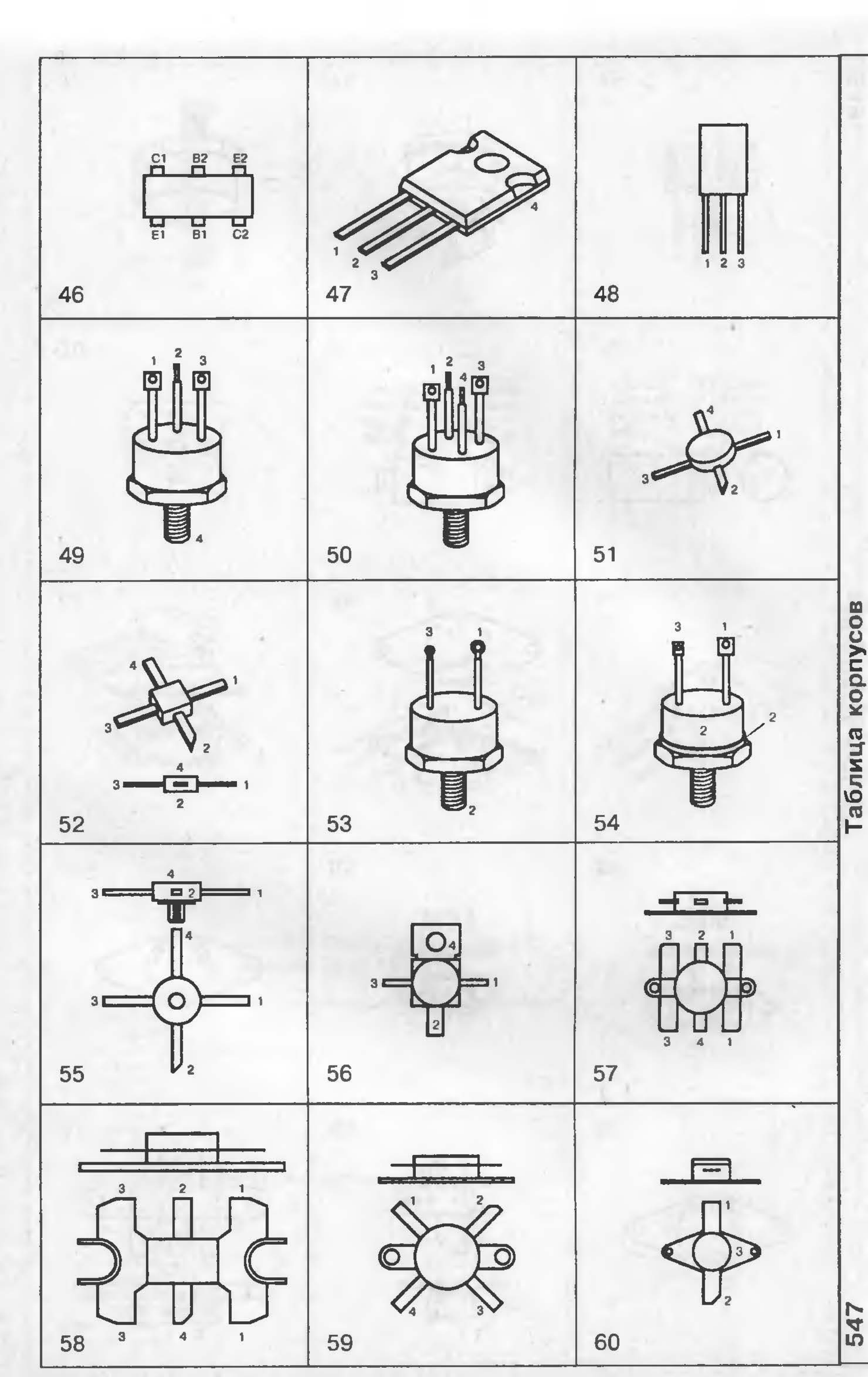
Наличие демпферного диода и номинал встроенного резистора R_{BE} указано во второй колонке таблицы параметров электронных полупроводниковых приборов

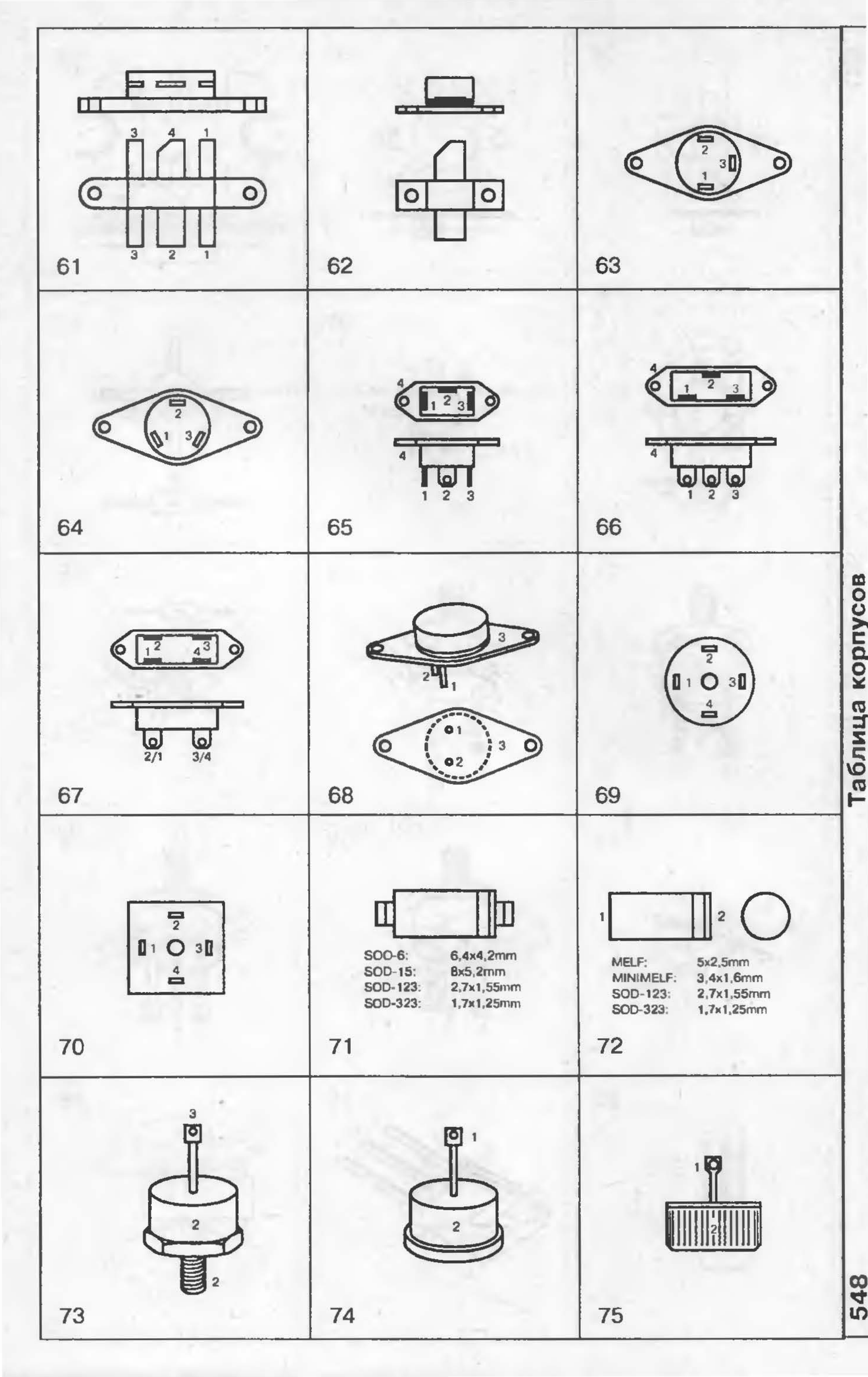
ТАБЛИЦА КОРПУСОВ (ЦОКОЛЕВКА, ВНЕШНИЙ ВИД)

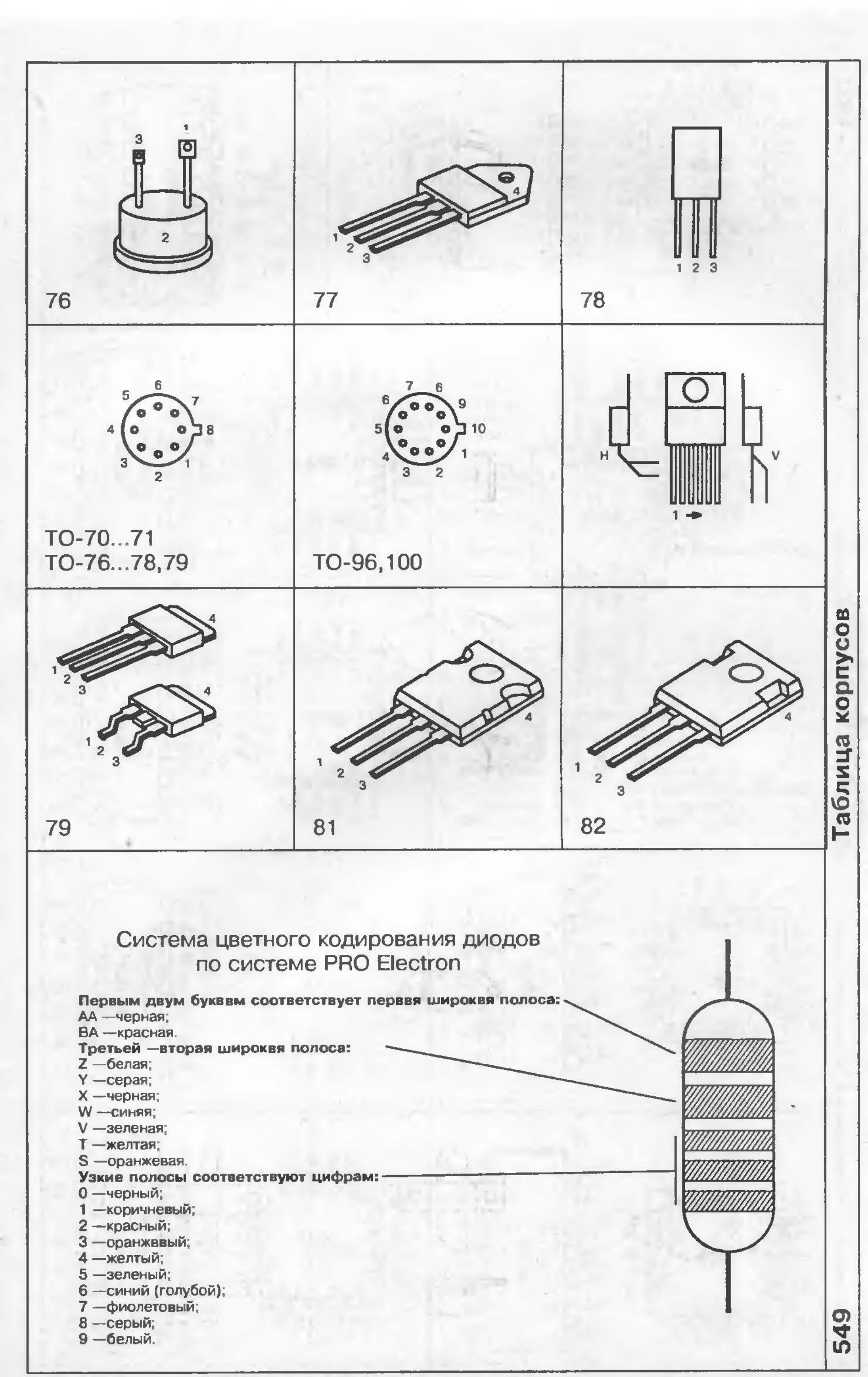
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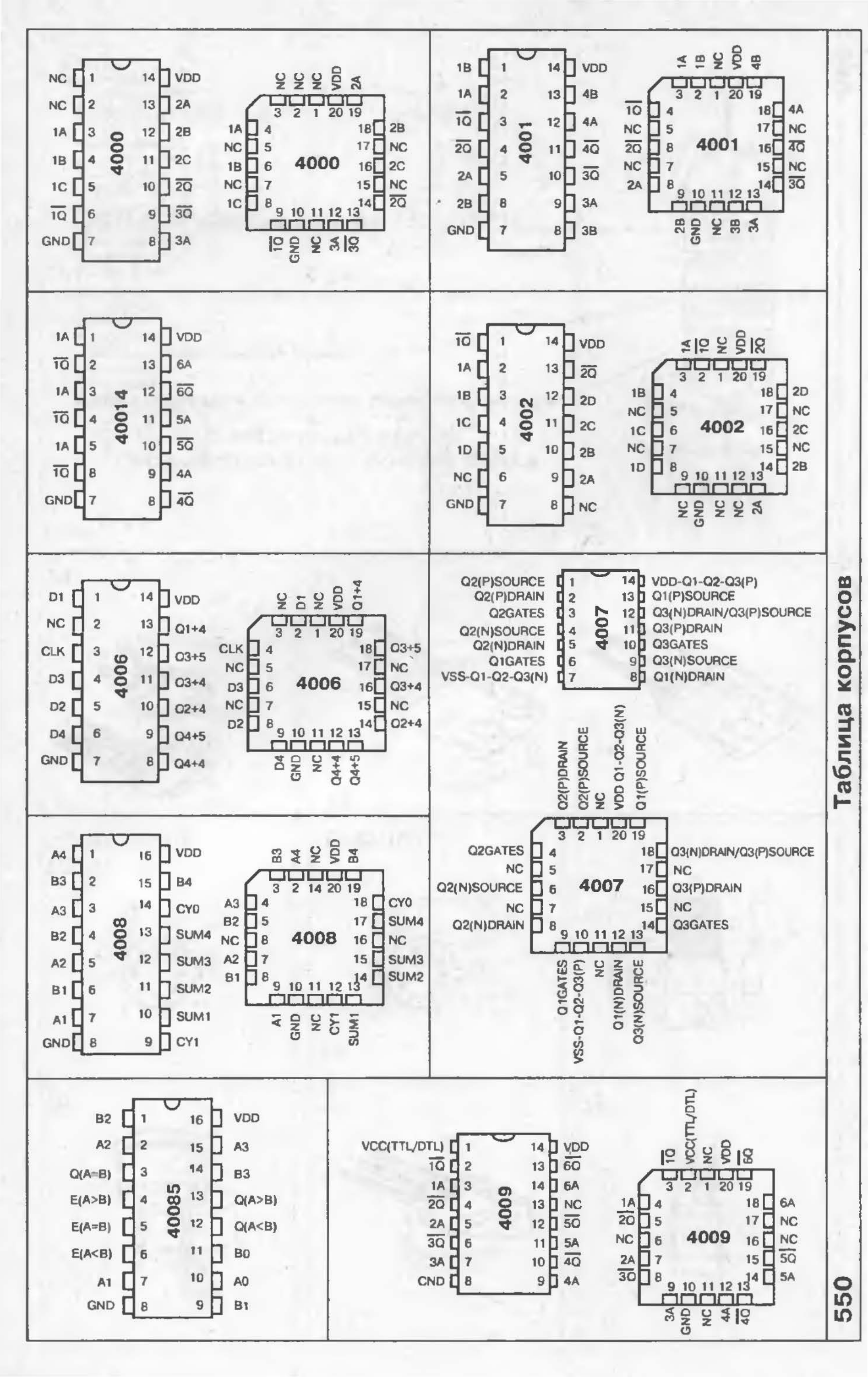

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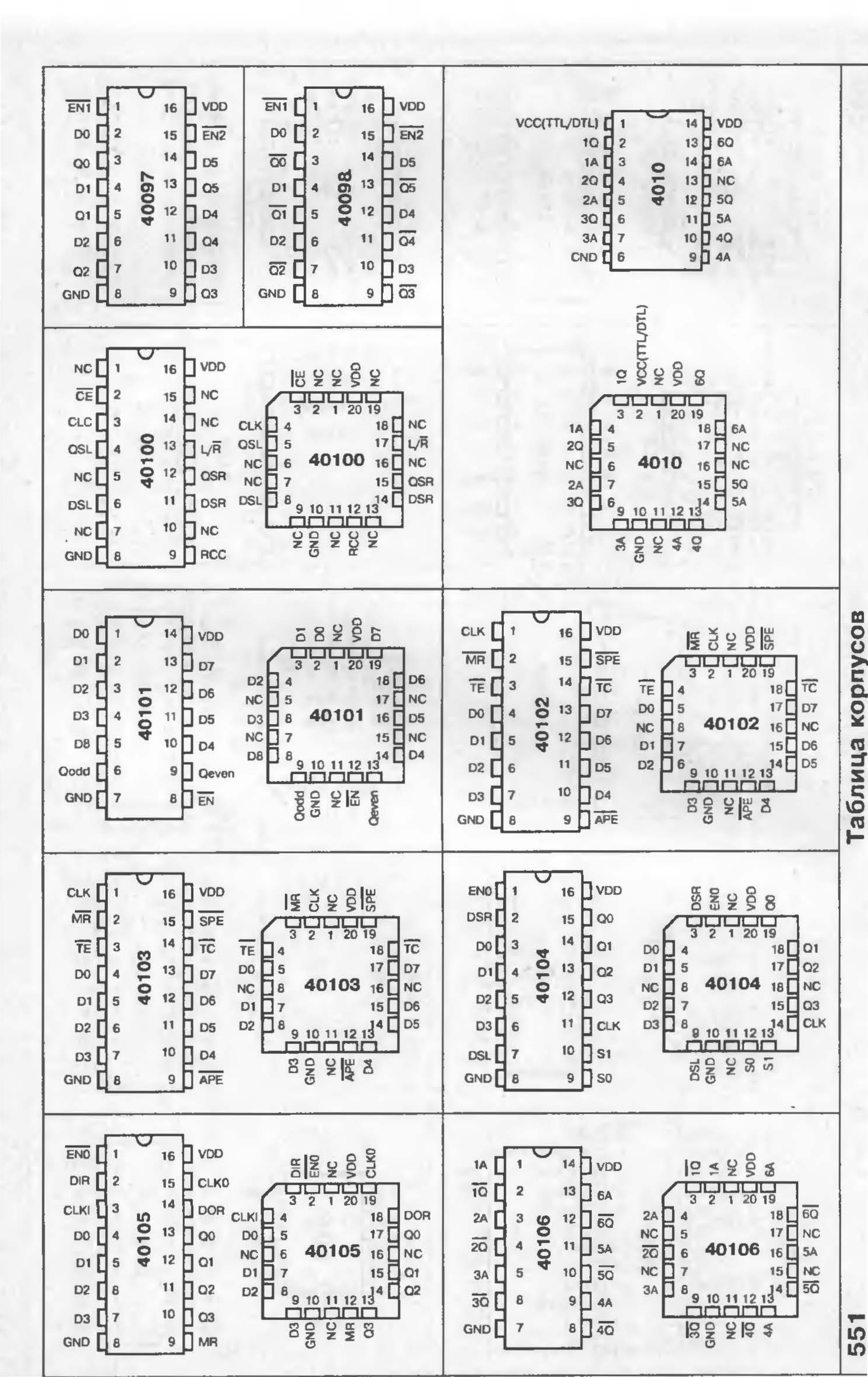

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SOD-6: 6,4x4,2mm
SOD-15: 8x5,2mm
SOD-123: 2,7x1,55mm
SOD-323: 1,7x1,25mm
71
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MELF: 5x2,5mm
MINIMELF: 3,4x1,6mm
SOD-123: 2,7x1,55mm
SOD-323: 1,7x1,25mm
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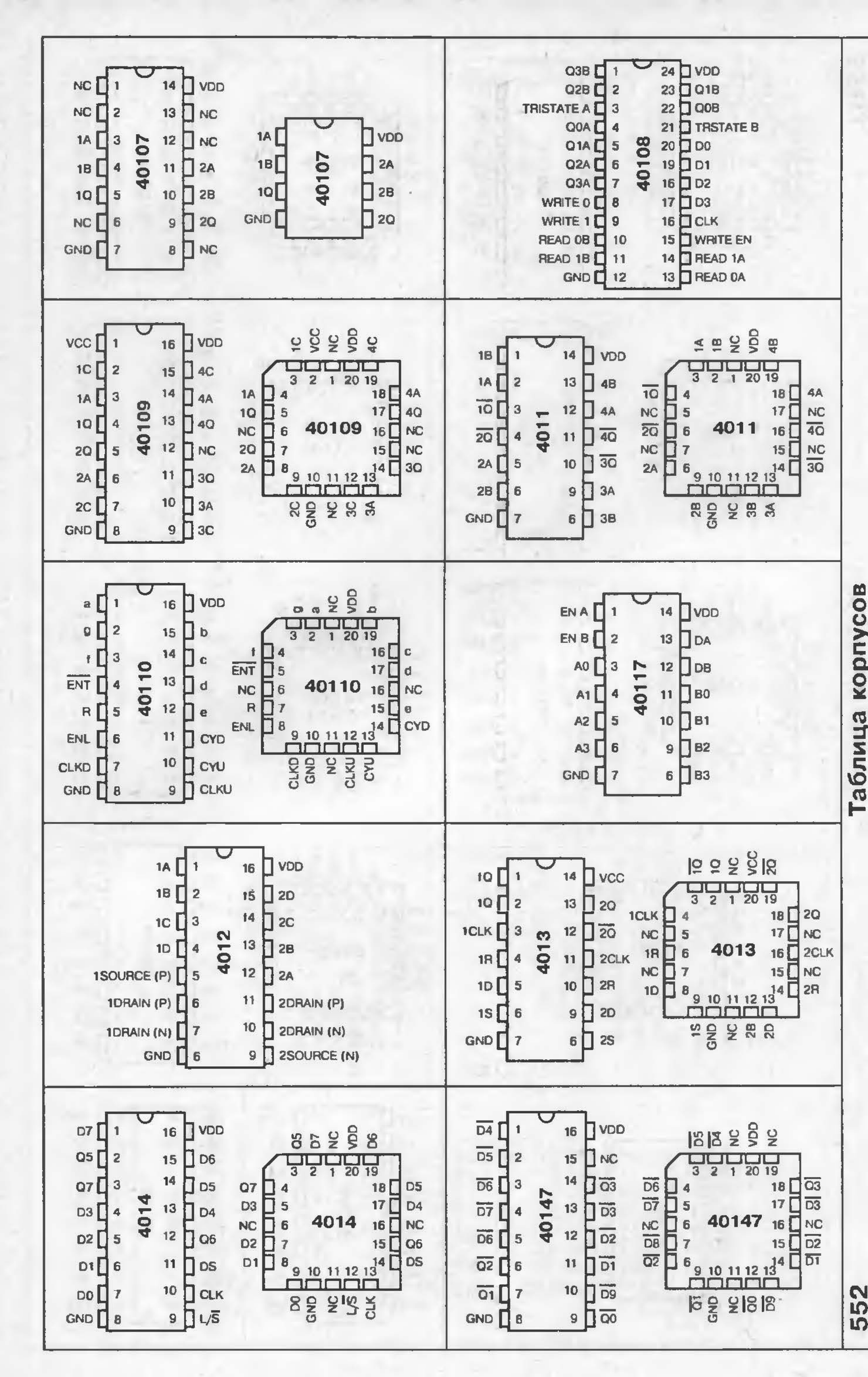


Система цветного кодирования диодов по системе PRO Electron

Первым двум букввм соответствует перввя широквя полоса:
AA —черная;
BA —красная.
Третьей —вторая широквя полоса:
Z —белая;
Y —серая;
X —черная;
W —синяя;
V —зеленая;
T —желтая;
S —оранжевая.
Узкие полосы соответствуют цифрам:
0 —черный;
1 —коричневый;
2 —красный;
3 —оранжввый;
4 —желтый;
5 —зеленый;
6 —синий (голубой);
7 —фиолетовый;
8 —серый;
9 —белый.


4000
NC NC 1A 1B 1C 1Q GND 3A 3Q 2Q 2C 2B 2A VDD
4001
1B 1A 1Q 2Q 2A 2B GND 3B 3A 3Q 4Q 4A 4B VDD
40014
1A 1Q 1A 1Q 1A 1Q GND 4Q 4A 5Q 5A 6Q 6A VDD
4002
1Q 1A 1B 1C 1D NC GND NC 2A 2B 2C 2D 2Q VDD
4006
D1 NC CLK D3 D2 D4 GND Q4+4 Q4+5 Q2+4 Q3+4 Q3+5 Q1+4 VDD
4007
Q2(P)SOURCE Q2(P)DRAIN Q2GATES Q2(N)SOURCE Q2(N)DRAIN Q1GATES VSS-Q1-Q2-Q3(N)
Q1(N)DRAIN Q3(N)SOURCE Q3GATES Q3(P)DRAIN Q3(N)DRAIN/Q3(P)SOURCE Q1(P)SOURCE VDD-Q1-Q2-Q3(P)
4008
A4 B3 A3 B2 A2 B1 A1 GND CY1 SUM1 SUM2 SUM3 SUM4 CY0 B4 VDD
40085
B2 A2 Q(A=B) E(A>B) E(A=B) E(A<B) A1 GND B1 A0 B0 Q(A<B) Q(A>B) B3 A3 VDD
4009
VCC(TTL/DTL) 1Q 1A 2Q 2A 3Q 3A CND 4A 4Q 5A 5Q NC 6A 6Q VDD


40097
EN1 1, D0 2, Q0 3, D1 4, Q1 5, D2 6, Q2 7, GND 8
9 Q3, 10 D3, 11 Q4, 12 D4, 13 Q5, 14 D5, 15 EN2, 16 VDD
40098
EN1 1, D0 2, Q0 3, D1 4, Q1 5, D2 6, Q2 7, GND 8
9 Q3, 10 D3, 11 Q4, 12 D4, 13 Q5, 14 D5, 15 EN2, 16 VDD
4010
VCC(TTL/DTL) 1, 1Q 2, 1A 3, 2Q 4, 2A 5, 3Q 6, 3A 7, CND 6
9 4A, 10 4Q, 11 5A, 12 5Q, 13 NC, 14 6A, 13 6Q, 14 VDD
4010
1Q 3, VCC(TTL/DTL) 2, NC 1, VDD 20, 6Q 19
1A 4, 2Q 5, NC 6, 2A 7, 3Q 6
18 6A, 17 NC, 16 NC, 15 5Q, 14 5A
9 3A, 10 GND, 11 NC, 12 4A, 13 4Q
40100
NC 1, CE 2, CLC 3, QSL 4, NC 5, DSL 6, NC 7, GND 8
9 RCC, 10 NC, 11 DSR, 12 QSR, 13 L/R, 14 NC, 15 NC, 16 VDD
40100
CE 3, NC 2, NC 1, VDD 20, NC 19
CLK 4, QSL 5, NC 6, NC 7, DSL 8
18 NC, 17 L/R, 16 NC, 15 QSR, 14 DSR
9 NC, 10 GND, 11 NC, 12 RCC, 13 NC
40101
D0 1, D1 2, D2 3, D3 4, D8 5, Qodd 6, GND 7
8 EN, 9 Qeven, 10 D4, 11 D5, 12 D6, 13 D7, 14 VDD
40101
D1 3, D0 2, NC 1, VDD 20, D7 19
D2 4, NC 5, D3 8, NC 7, D8 8
18 D6, 17 NC, 16 D5, 15 NC, 14 D4
9 Qodd, 10 GND, 11 NC, 12 EN, 13 Qeven
40102
CLK 1, MR 2, TE 3, D0 4, D1 5, D2 6, D3 7, GND 8
9 APE, 10 D4, 11 D5, 12 D6, 13 D7, 14 TC, 15 SPE, 16 VDD
40102
MR 3, CLK 2, NC 1, VDD 20, SPE 19
TE 4, D0 5, NC 8, D1 7, D2 6
18 TC, 17 D7, 16 NC, 15 D6, 14 D5
9 D3, 10 GND, 11 NC, 12 APE, 13 D4
40103
CLK 1, MR 2, TE 3, D0 4, D1 5, D2 6, D3 7, GND 8
9 APE, 10 D4, 11 D5, 12 D6, 13 D7, 14 TC, 15 SPE, 16 VDD
40103
MR 3, CLK 2, NC 1, VDD 20, SPE 19
TE 4, D0 5, NC 8, D1 7, D2 8
18 TC, 17 D7, 16 NC, 15 D6, 14 D5
9 D3, 10 GND, 11 NC, 12 APE, 13 D4
40104
EN0 1, DSR 2, D0 3, D1 4, D2 5, D3 6, DSL 7, GND 8
9 S0, 10 S1, 11 CLK, 12 Q3, 13 Q2, 14 Q1, 15 Q0, 16 VDD
40104
DSR 3, EN0 2, NC 1, VDD 20, Q0 19
D0 4, D1 5, NC 8, D2 7, D3 8
18 Q1, 17 Q2, 18 NC, 15 Q3, 14 CLK
9 DSL, 10 GND, 11 NC, 12 S0, 13 S1
40105
EN0 1, DIR 2, CLKI 3, D0 4, D1 5, D2 8, D3 7, GND 8
9 MR, 10 Q3, 11 Q2, 12 Q1, 13 Q0, 14 DOR, 15 CLKO, 16 VDD
40105
DIR 3, EN0 2, NC 1, VDD 20, CLKO 19
CLKI 4, D0 5, NC 6, D1 7, D2 8
18 DOR, 17 Q0, 16 NC, 15 Q1, 14 Q2
9 D3, 10 GND, 11 NC, 12 MR, 13 Q3
40106
1A 1, 1Q 2, 2A 3, 2Q 4, 3A 5, 3Q 8, GND 7
8 4Q, 9 4A, 10 5Q, 11 5A, 12 6Q, 13 6A, 14 VDD
40106
1Q 3, 1A 2, NC 1, VDD 20, 6A 19
2A 4, NC 5, 2Q 6, NC 7, 3A 8
18 6Q, 17 NC, 16 5A, 15 NC, 14 5Q
9 3Q, 10 GND, 11 NC, 12 4Q, 13 4A


40107
NC 1 14 VDD
NC 2 13 NC
1A 3 12 NC
1B 4 11 2A
1Q 5 10 2B
NC 6 9 2Q
GND 7 8 NC
40107
1A VDD
1B 2A
1Q 2B
GND 2Q
40108
Q3B 1 24 VDD
Q2B 2 23 Q1B
TRISTATE A 3 22 Q0B
Q0A 4 21 TRSTATE B
Q1A 5 20 D0
Q2A 6 19 D1
Q3A 7 16 D2
WRITE 0 8 17 D3
WRITE 1 9 16 CLK
READ 0B 10 15 WRITE EN
READ 1B 11 14 READ 1A
GND 12 13 READ 0A
40109
VCC 1 16 VDD
1C 2 15 4C
1A 3 14 4A
1Q 4 13 4Q
2Q 5 12 NC
2A 6 11 3Q
2C 7 10 3A
GND 8 9 3C
40109
1C VCC NC VDD 4C
3 2 1 20 19
1A 4 18 4A
1Q 5 17 4Q
NC 6 16 NC
2Q 7 15 NC
2A 8 14 3Q
9 10 11 12 13
2C GND NC 3C 3A
4011
1B 1 14 VDD
1A 2 13 4B
1Q 3 12 4A
2Q 4 11 4Q
2A 5 10 3Q
2B 6 9 3A
GND 7 6 3B
4011
1A 1B NC VDD 4B
3 2 1 20 19
1Q 4 18 4A
NC 5 17 NC
2Q 6 16 4Q
NC 7 15 NC
2A 6 14 3Q
9 10 11 12 13
2B GND NC 3B 3A
40110
a 1 16 VDD
g 2 15 b
f 3 14 c
ENT 4 13 d
R 5 12 e
ENL 6 11 CYD
CLKD 7 10 CYU
GND 8 9 CLKU
40110
g a NC VDD b
3 2 1 20 19
f 4 16 c
ENT 5 17 d
NC 6 16 NC
R 7 15 e
ENL 8 14 CYD
9 10 11 12 13
CLKD GND NC CLKU CYU
40117
EN A 1 14 VDD
EN B 2 13 DA
A0 3 12 DB
A1 4 11 B0
A2 5 10 B1
A3 6 9 B2
GND 7 6 B3
4012
1A 1 16 VDD
1B 2 15 2D
1C 3 14 2C
1D 4 13 2B
1SOURCE (P) 5 12 2A
1DRAIN (P) 6 11 2DRAIN (P)
1DRAIN (N) 7 10 2DRAIN (N)
GND 6 9 2SOURCE (N)
4013
1Q 1 14 VCC
1Q 2 13 2Q
1CLK 3 12 2Q
1R 4 11 2CLK
1D 5 10 2R
1S 6 9 2D
GND 7 6 2S
4013
1Q 1Q NC VCC 2Q
3 2 1 20 19
1CLK 4 18 2Q
NC 5 17 NC
1R 6 16 2CLK
NC 7 15 NC
1D 8 14 2R
9 10 11 12 13
1S GND NC 2B 2D
4014
D7 1 16 VDD
Q5 2 15 D6
Q7 3 14 D5
D3 4 13 D4
D2 5 12 Q6
D1 6 11 DS
D0 7 10 CLK
GND 8 9 L/S
4014
Q5 D7 NC VDD D6
3 2 1 20 19
Q7 4 18 D5
D3 5 17 D4
NC 6 16 NC
D2 7 15 Q6
D1 8 14 DS
9 10 11 12 13
D0 GND NC L/S CLK
40147
D4 1 16 VDD
D5 2 15 NC
D6 3 14 Q3
D7 4 13 D3
D6 5 12 D2
Q2 6 11 D1
Q1 7 10 D9
GND 8 9 Q0
40147
D5 D4 NC VDD NC
3 2 1 20 19
D6 4 18 Q3
D7 5 17 D3
NC 6 16 NC
D8 7 15 D2
Q2 6 14 D1
9 10 11 12 13
Q1 GND NC Q0 D9

4015

2CLK	1	16	VDD
2Q3	2	15	2D
1Q2	3	14	2R
1Q1	4	13	2Q0
1Q0	5	12	2Q1
1R	6	11	2Q2
1D	7	10	1Q3
GND	8	9	1CLK

4015 (PLCC): 3 2Q3, 2 2CLK, 1 NC, 20 VDD, 19 2D; 4 1Q2, 5 1Q1, 8 NC, 7 1Q0, 8 1R; 18 2R, 17 2Q0, 16 NC, 15 2Q1, 14 2Q2; 9 1D, 10 GND, 11 NC, 12 1CLK, 13 1Q3

4016

1I/O	1	14	VDD
1O/I	2	13	1C
2O/I	3	12	4C
2I/O	4	11	4I/O
2C	5	10	4O/I
3C	6	9	3O/I
GND	7	8	3I/O

4016 (PLCC): 3 1O/I, 2 1I/O, 1 NC, 20 VDD, 19 1C; 4 2O/I, 5 NC, 6 2I/O, 7 NC, 8 2C; 18 4C, 17 NC, 16 4I/O, 15 NC, 14 4O/I; 9 3C, 10 GND, 11 NC, 12 3I/O, 13 3O/I

40160, **40161**, **40162**, **40163**

$\overline{CLR}$	1	16	VDD
CLK	2	15	CY
D0	3	14	Q0
D1	4	13	Q1
D2	5	12	Q2
D3	6	11	Q3
EN1	7	10	EN2
GND	8	9	$\overline{SI}$

40160, **40161**, **40162**, **40163** (PLCC): 3 CLK, 2 $\overline{CLR}$, 1 NC, 20 VDD, 19 CY; 4 D0, 5 D1, 6 NC, 7 D2, 8 D3; 18 Q0, 17 Q1, 16 NC, 15 Q2, 14 Q3; 9 EN1, 10 GND, 11 NC, 12 $\overline{S}$, 13 EN2

4017

Q5	1	16	VDD
Q1	2	15	CLR
Q0	3	14	CLK
Q2	4	13	$\overline{CLKEN}$
Q6	5	12	$\overline{CY0}$
Q7	6	11	Q9
Q3	7	10	Q4
GND	8	9	Q8

4017 (PLCC): 3 Q1, 2 Q5, 1 NC, 20 VDD, 19 CLR; 4 Q0, 5 Q2, 8 NC, 7 Q6, 8 Q7; 18 CLK, 17 $\overline{CLKEN}$, 16 NC, 15 $\overline{CY0}$, 14 Q9; 9 Q3, 10 GND, 11 NC, 12 Q8, 13 Q4

40174

$\overline{CLR}$	1	16	VDD
1Q	2	15	6Q
1D	3	14	6D
2D	4	13	5D
2Q	5	12	5Q
3D	6	11	4D
3Q	7	10	4Q
GND	8	9	CLK

40174 (PLCC): 3 1Q, 2 $\overline{CLR}$, 1 NC, 20 VDD, 19 6Q; 4 1D, 5 2D, 6 NC, 7 2Q, 8 3D; 18 6D, 17 5D, 16 NC, 15 5Q, 14 4D; 9 3Q, 10 GND, 11 NC, 12 CLK, 13 4Q

40175

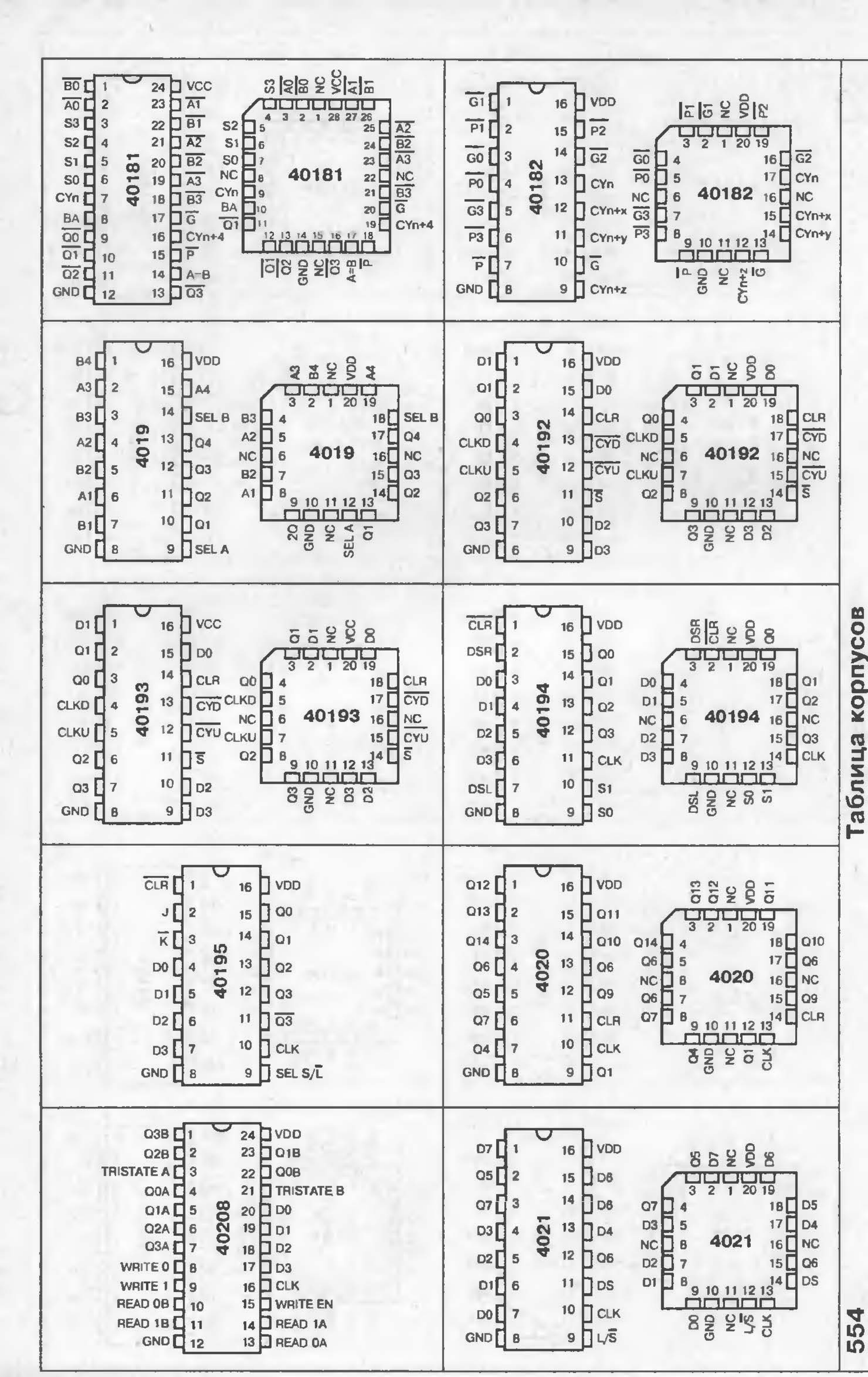
$\overline{CLR}$	1	16	VDD
1Q	2	15	4Q
$\overline{1Q}$	3	14	$\overline{4Q}$
1D	4	13	4D
2D	5	12	3D
$\overline{2Q}$	6	11	$\overline{3Q}$
2Q	7	10	3Q
GND	6	9	CLK

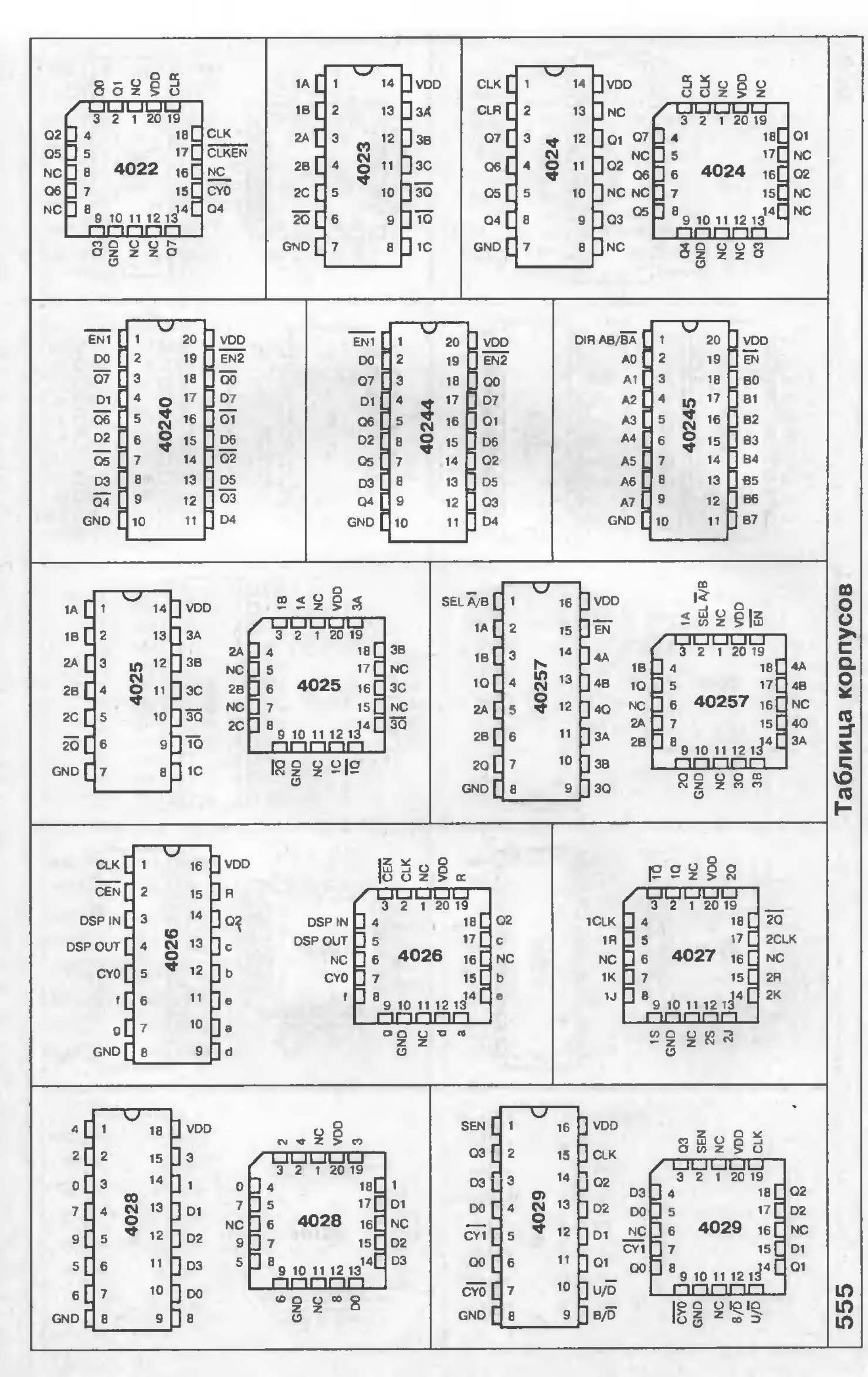
40175 (PLCC): 3 1Q, 2 $\overline{CLR}$, 1 NC, 20 VDD, 19 4Q; 4 $\overline{1Q}$, 5 1D, 6 NC, 7 2D, 8 $\overline{2Q}$; 18 $\overline{4Q}$, 17 4D, 16 NC, 15 3D, 14 $\overline{3Q}$; 9 2Q, 10 GND, 11 NC, 12 CLK, 13 3Q

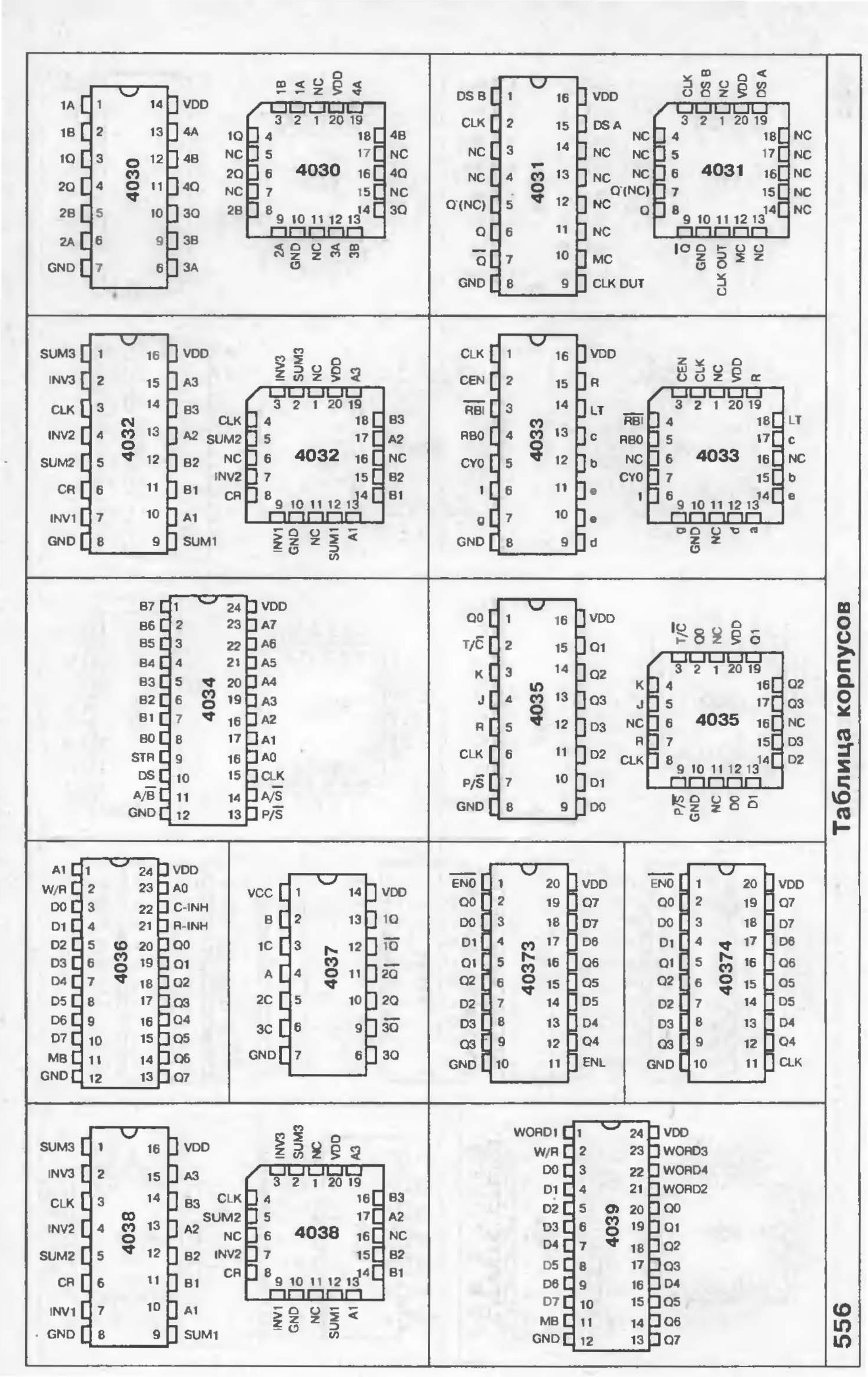
4018

DS	1	18	VDD
D0	2	15	MR
D1	3	14	CLK
$\overline{Q1}$	4	13	$\overline{Q4}$
$\overline{Q0}$	5	12	D4
$\overline{Q2}$	8	11	$\overline{Q3}$
D2	7	10	PL
GND	8	9	D3

4018 (PLCC): 3 D0, 2 DS, 1 NC, 20 VDD, 19 MR; 4 D1, 5 $\overline{Q1}$, 6 NC, 7 $\overline{Q0}$, 8 $\overline{Q2}$; 18 CLK, 17 $\overline{Q4}$, 16 NC, 15 D4, 14 $\overline{Q3}$; 9 D2, 10 GND, 11 NC, 12 D3, 13 PL


40181
B0 A0 S3 S2 S1 S0 CYn BA Q0 Q1 Q2 GND
VCC A1 B1 A2 B2 A3 B3 G CYn+4 P A=B Q3
40182
G1 P1 G0 P0 G3 P3 P GND
VDD P2 G2 CYn CYn+x CYn+y G CYn+z
4019
B4 A3 B3 A2 B2 A1 B1 GND
VDD A4 SEL B Q4 Q3 Q2 Q1 SEL A
40192
D1 Q1 Q0 CLKD CLKU Q2 Q3 GND
VDD D0 CLR CYD CYU S D2 D3
40193
D1 Q1 Q0 CLKD CLKU Q2 Q3 GND
VCC D0 CLR CYD CYU S D2 D3
40194
CLR DSR D0 D1 D2 D3 DSL GND
VDD Q0 Q1 Q2 Q3 CLK S1 S0
40195
CLR J K D0 D1 D2 D3 GND
VDD Q0 Q1 Q2 Q3 Q3 CLK SEL S/L
4020
Q12 Q13 Q14 Q6 Q5 Q7 Q4 GND
VDD Q11 Q10 Q6 Q9 CLR CLK Q1
40208
Q3B Q2B TRISTATE A Q0A Q1A Q2A Q3A WRITE 0 WRITE 1 READ 0B READ 1B GND
VDD Q1B Q0B TRISTATE B D0 D1 D2 D3 CLK WRITE EN READ 1A READ 0A
4021
D7 Q5 Q7 D3 D2 D1 D0 GND
VDD D6 D8 D4 Q6 DS CLK L/S


4022: NC Q1 Q0 Q2 Q5 NC Q6 NC Q3 GND NC NC Q7 Q4 CY0 NC CLKEN CLK CLR VDD
4023: 1A 1B 2A 2B 2C 2Q GND 1C 1Q 3Q 3C 3B 3A VDD
4024: CLK CLR Q7 Q6 Q5 Q4 GND NC Q3 NC Q2 Q1 NC VDD
4024: NC CLR CLK Q7 NC Q6 NC Q5 Q4 GND NC NC Q3 NC NC Q2 NC Q1 NC VDD
40240: EN1 D0 Q7 D1 Q6 D2 Q5 D3 Q4 GND D4 Q3 D5 Q2 D6 Q1 D7 Q0 EN2 VDD
40244: EN1 D0 Q7 D1 Q6 D2 Q5 D3 Q4 GND D4 Q3 D5 Q2 D6 Q1 D7 Q0 EN2 VDD
40245: DIR AB/BA A0 A1 A2 A3 A4 A5 A6 A7 GND B7 B6 B5 B4 B3 B2 B1 B0 EN VDD
4025: 1A 1B 2A 2B 2C 2Q GND 1C 1Q 3Q 3C 3B 3A VDD
4025: NC 1A 1B 2A NC 2B NC 2C 2Q GND NC 1C 1Q 3Q NC 3C NC 3B 3A VDD
40257: SEL A/B 1A 1B 1Q 2A 2B 2Q GND 3Q 3B 3A 4Q 4B 4A EN VDD
40257: NC SEL A/B 1A 1B 1Q NC 2A 2B 2Q GND NC 3Q 3B 3A 4Q NC 4B 4A EN VDD
4026: CLK CEN DSP IN DSP OUT CY0 f g GND d a e b c Q2 R VDD
4026: NC CLK CEN DSP IN DSP OUT NC CY0 f g GND NC d a e b NC c Q2 R VDD
4027: NC 1Q 1Q 1CLK 1R NC 1K 1J 1S GND NC 2S 2J 2K 2R NC 2CLK 2Q 2Q VDD
4028: 4 2 0 7 9 5 6 GND 8 D0 D3 D2 D1 1 3 VDD
4028: NC 4 2 0 7 NC 9 5 6 GND NC 8 D0 D3 D2 NC D1 1 3 VDD
4029: SEN Q3 D3 D0 CY1 Q0 CY0 GND B/D U/D Q1 D1 D2 Q2 CLK VDD
4029: NC SEN Q3 D3 D0 NC CY1 Q0 CY0 GND NC 8/D U/D Q1 D1 NC D2 Q2 CLK VDD


4030
1A 1 14 VDD
1B 2 13 4A
1Q 3 12 4B
2Q 4 11 4Q
2B 5 10 3Q
2A 6 9 3B
GND 7 8 3A
4030
1B 1A NC VDD 4A
3 2 1 20 19
1Q 4 18 4B
NC 5 17 NC
2Q 6 16 4Q
NC 7 15 NC
2B 8 14 3Q
9 10 11 12 13
2A GND NC 3A 3B
4031
DS B 1 16 VDD
CLK 2 15 DS A
NC 3 14 NC
NC 4 13 NC
Q'(NC) 5 12 NC
Q 6 11 NC
Q̄ 7 10 MC
GND 8 9 CLK DUT
4031
CLK DS B NC VDD DS A
3 2 1 20 19
NC 4 18 NC
NC 5 17 NC
NC 6 16 NC
Q'(NC) 7 15 NC
Q 8 14 NC
9 10 11 12 13
Q̄ GND CLK OUT MC NC
4032
SUM3 1 16 VDD
INV3 2 15 A3
CLK 3 14 B3
INV2 4 13 A2
SUM2 5 12 B2
CR 6 11 B1
INV1 7 10 A1
GND 8 9 SUM1
4032
INV3 SUM3 NC VDD A3
3 2 1 20 19
CLK 4 18 B3
SUM2 5 17 A2
NC 6 16 NC
INV2 7 15 B2
CR 8 14 B1
9 10 11 12 13
INV1 GND NC SUM1 A1
4033
CLK 1 16 VDD
CEN 2 15 R
RBI 3 14 LT
RB0 4 13 c
CY0 5 12 b
1 6 11 e
g 7 10 e
GND 8 9 d
4033
CEN CLK NC VDD R
3 2 1 20 19
RBI 4 18 LT
RB0 5 17 c
NC 6 16 NC
CY0 7 15 b
1 6 14 e
9 10 11 12 13
g GND NC d a
4034
B7 1 24 VDD
B6 2 23 A7
B5 3 22 A6
B4 4 21 A5
B3 5 20 A4
B2 6 19 A3
B1 7 16 A2
B0 8 17 A1
STR 9 16 A0
DS 10 15 CLK
A/B̄ 11 14 A/S̄
GND 12 13 P/S̄
4035
Q0 1 16 VDD
T/C̄ 2 15 Q1
K 3 14 Q2
J 4 13 Q3
R 5 12 D3
CLK 6 11 D2
P/S̄ 7 10 D1
GND 8 9 D0
4035
T/C̄ Q0 NC VDD Q1
3 2 1 20 19
K 4 16 Q2
J 5 17 Q3
NC 6 16 NC
R 7 15 D3
CLK 8 14 D2
9 10 11 12 13
P/S̄ GND NC D0 D1
4036
A1 1 24 VDD
W/R 2 23 A0
D0 3 22 C-INH
D1 4 21 R-INH
D2 5 20 Q0
D3 6 19 Q1
D4 7 18 Q2
D5 8 17 Q3
D6 9 16 Q4
D7 10 15 Q5
MB 11 14 Q6
GND 12 13 Q7
4037
VCC 1 14 VDD
B 2 13 1Q
1C 3 12 1Q̄
A 4 11 2Q̄
2C 5 10 2Q
3C 6 9 3Q̄
GND 7 6 3Q
40373
EN0 1 20 VDD
Q0 2 19 Q7
D0 3 18 D7
D1 4 17 D6
Q1 5 16 Q6
Q2 6 15 Q5
D2 7 14 D5
D3 8 13 D4
Q3 9 12 Q4
GND 10 11 ENL
40374
EN0 1 20 VDD
Q0 2 19 Q7
D0 3 18 D7
D1 4 17 D6
Q1 5 16 Q6
Q2 6 15 Q5
D2 7 14 D5
D3 8 13 D4
Q3 9 12 Q4
GND 10 11 CLK
4038
SUM3 1 16 VDD
INV3 2 15 A3
CLK 3 14 B3
INV2 4 13 A2
SUM2 5 12 B2
CR 6 11 B1
INV1 7 10 A1
GND 8 9 SUM1
4038
INV3 SUM3 NC VDD A3
3 2 1 20 19
CLK 4 16 B3
SUM2 5 17 A2
NC 6 16 NC
INV2 7 15 B2
CR 8 14 B1
9 10 11 12 13
INV1 GND NC SUM1 A1
4039
WORD1 1 24 VDD
W/R 2 23 WORD3
D0 3 22 WORD4
D1 4 21 WORD2
D2 5 20 Q0
D3 6 19 Q1
D4 7 18 Q2
D5 8 17 Q3
D6 9 16 Q4
D7 10 15 Q5
MB 11 14 Q6
GND 12 13 Q7

4040

Pin	DIP	PLCC
1	Q12	NC
2	Q6	Q12
3	Q5	Q6
4	Q7	Q5
5	Q4	Q7
6	Q3	NC
7	Q2	Q4
8	GND	Q3
9	Q1	Q2
10	CLK	GND
11	CLR	NC
12	Q9	Q1
13	Q8	CLK
14	Q10	CLR
15	Q11	Q9
16	VDD	NC
17		Q8
18		Q10
19		Q11
20		VDD

4041

Pin	DIP	PLCC
1	1Q	NC
2	$\overline{1Q}$	1Q
3	1A	$\overline{1Q}$
4	2Q	1A
5	$\overline{2Q}$	NC
6	2A	2Q
7	GND	NC
8	3Q	$\overline{2Q}$
9	$\overline{3Q}$	2A
10	3A	GND
11	4Q	NC
12	$\overline{4Q}$	3Q
13	4A	$\overline{3Q}$
14	VDD	3A
15		NC
16		4Q
17		NC
18		$\overline{4Q}$
19		4A
20		VDD

4042

Pin	DIP	PLCC
1	1Q	NC
2	2Q	1Q
3	$\overline{2Q}$	2Q
4	2D	$\overline{2Q}$
5	CLK	2D
6	POL	NC
7	4D	CLK
8	GND	POL
9	$\overline{4Q}$	4D
10	4Q	GND
11	3Q	NC
12	$\overline{3Q}$	$\overline{4Q}$
13	3D	4Q
14	1D	3Q
15	$\overline{1Q}$	$\overline{3Q}$
16	VDD	NC
17		3D
18		1D
19		$\overline{1Q}$
20		VDD

4043

Pin	DIP	PLCC
1	4Q	NC
2	1Q	4Q
3	1R	1Q
4	1S	1R
5	EN	1S
6	2S	NC
7	2R	EN
8	GND	2S
9	2Q	2R
10	3Q	GND
11	3R	NC
12	3S	2Q
13	NC	3Q
14	4S	3R
15	4R	3S
16	VDD	NC
17		NC
18		4S
19		4R
20		VDD

4044

Pin	DIP	PLCC
1	4Q	NC
2	NC	4Q
3	$\overline{1S}$	1Q
4	$\overline{1R}$	$\overline{1S}$
5	EN	$\overline{1R}$
6	$\overline{2R}$	NC
7	$\overline{2S}$	EN
8	GND	$\overline{2R}$
9	2Q	$\overline{2S}$
10	3Q	GND
11	$\overline{3S}$	NC
12	$\overline{3R}$	2Q
13	1Q	3Q
14	$\overline{4R}$	$\overline{3S}$
15	$\overline{4S}$	$\overline{3R}$
16	VDD	NC
17		1Q
18		$\overline{4R}$
19		$\overline{4S}$
20		VDD

4045

Pin	DIP	PLCC
1	SP	NC
2	SN	SP
3	VDD	SN
4	NC	VDD
5	NC	NC
6	NC	NC
7	Q	NC
8	Q'	NC
9	NC	Q
10	NC	Q'
11	NC	NC
12	NC	NC
13	NC	NC
14	GND	NC
15	CLK2	NC
16	CLK1	NC
17		NC
18		GND
19		CLK2
20		CLK1

4046

Pin	DIP	PLCC
1	PCP	NC
2	PC1	PCP
3	COMP IN	PC1
4	VCD DUT	CDMP IN
5	INH	VCO OUT
6	Cext1	NC
7	Cext2	INH
8	GND	Cext1
9	VCO IN	Cext2
10	DEM OUT	GND
11	Rext1	NC
12	Rext2	VCO IN
13	PC2	DEM OUT
14	SIG IN	Rext2
15	PC3	Rext1
16	VDD	NC
17		PC2
18		SIG IN
19		PC3
20		VDD

4047

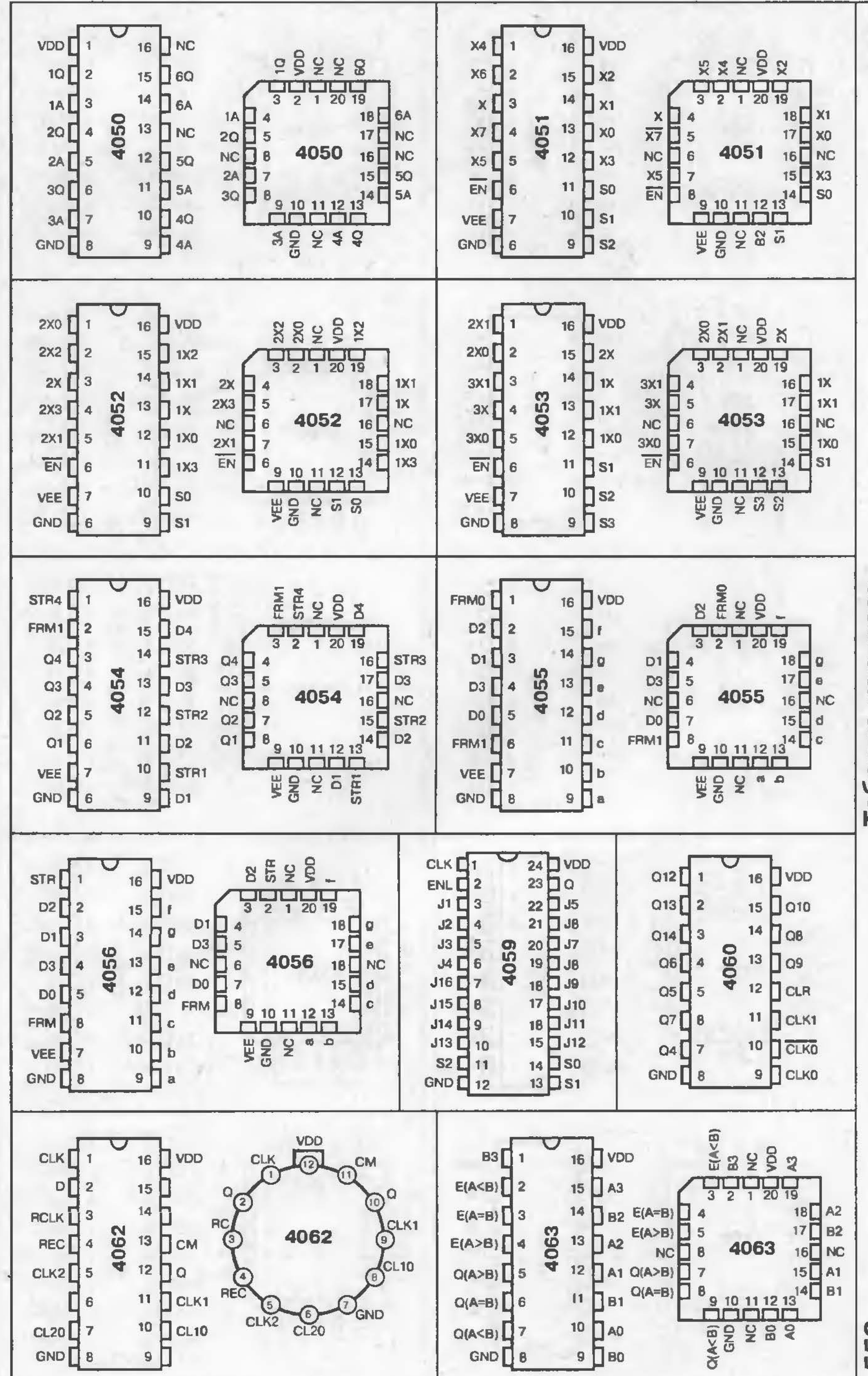
Pin	DIP	PLCC
1	Cext	NC
2	Rext	Cext
3	RCext	Rext
4	$\overline{AST}$	RCext
5	AST	NC
6	-TR	$\overline{AST}$
7	GND	NC
8	+TR	AST
9	R	-TR
10	Q	GND
11	$\overline{Q}$	NC
12	RETR	+TR
13	OSC OUT	R
14	VDD	Q
15		NC
16		$\overline{Q}$
17		NC
18		RETR
19		OSC OUT
20		VDD

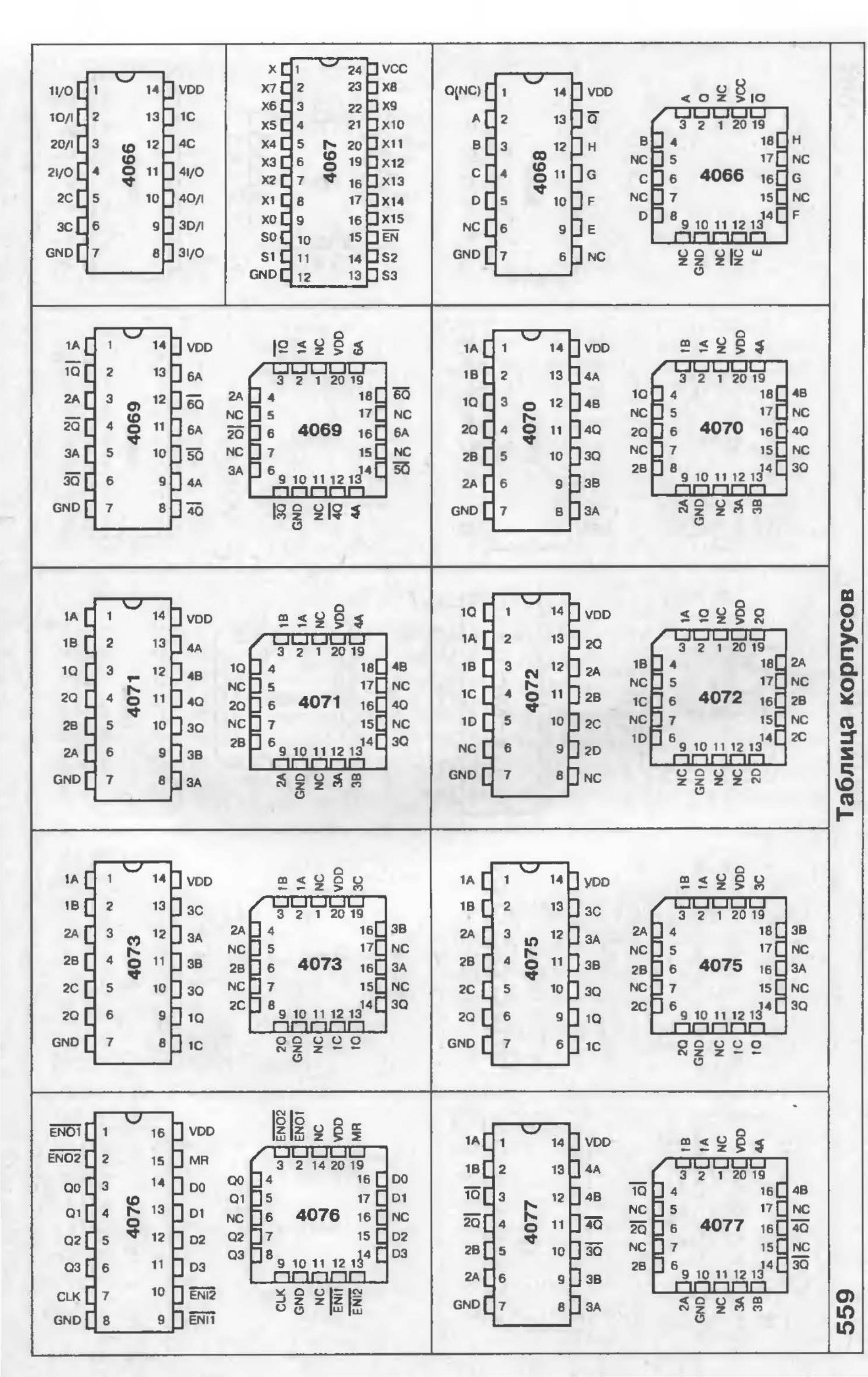
4048

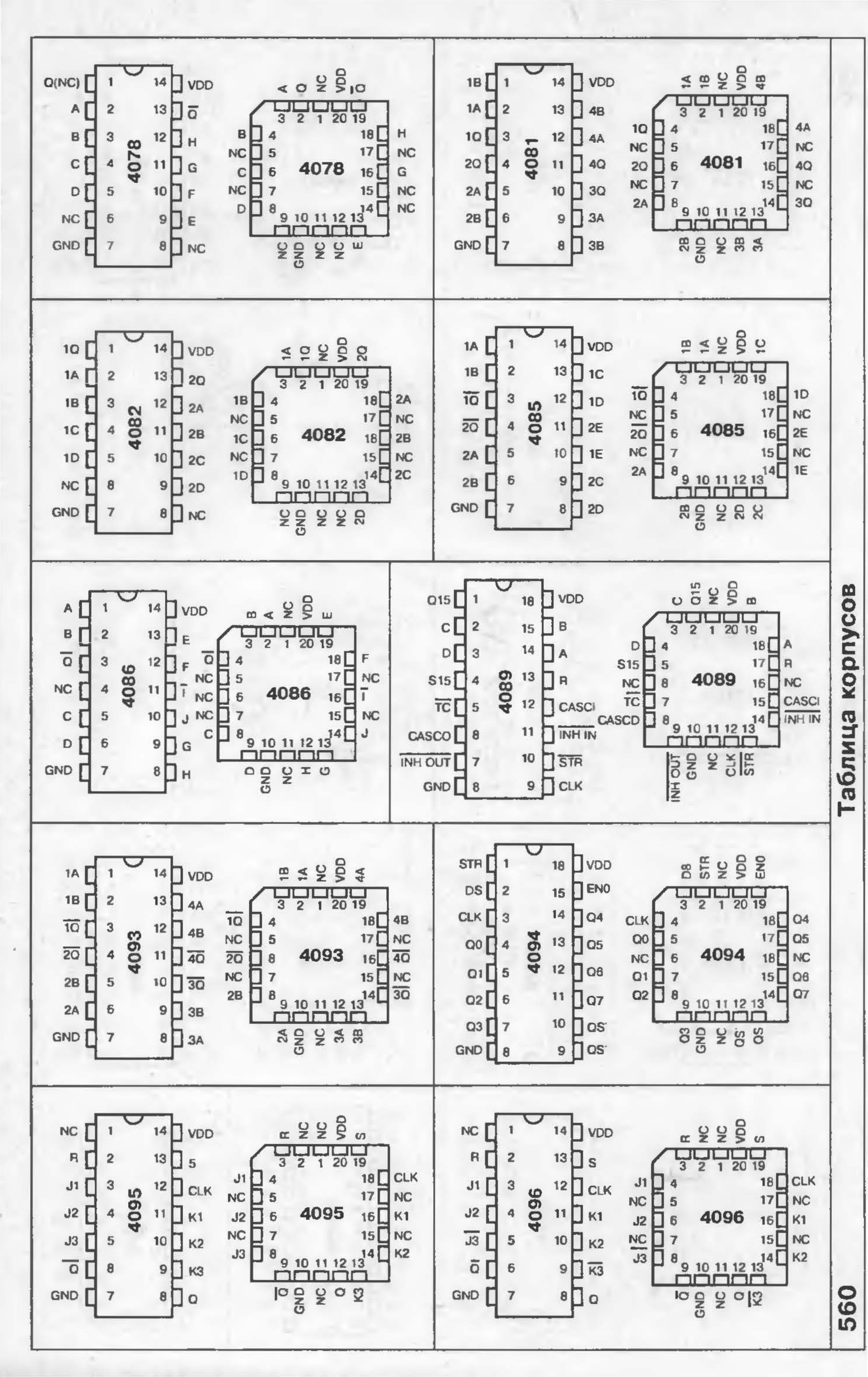
Pin	DIP	PLCC
1	Q	NC
2	EN	Q
3	H	EN
4	G	H
5	F	G
6	E	NC
7	S1	F
8	GND	E
9	S0	S1
10	S2	GND
11	D	NC
12	C	S0
13	B	S2
14	A	D
15	EXP	C
16	VDD	NC
17		B
18		A
19		EXP
20		VDD

4049

Pin	DIP	PLCC
1	VDD	NC
2	$\overline{1Q}$	VDD
3	1A	$\overline{1Q}$
4	$\overline{2Q}$	1A
5	2A	$\overline{2Q}$
6	$\overline{3Q}$	NC
7	3A	2A
8	GND	$\overline{3Q}$
9	4A	3A
10	$\overline{4Q}$	GND
11	5A	NC
12	$\overline{5Q}$	4A
13	NC	$\overline{4Q}$
14	6A	5A
15	$\overline{5Q}$	$\overline{5Q}$
16	NC	NC
17		NC
18		BA
19		$\overline{6Q}$
20		NC


4050
VDD 1, 1Q 2, 1A 3, 2Q 4, 2A 5, 3Q 6, 3A 7, GND 8
16 NC, 15 6Q, 14 6A, 13 NC, 12 5Q, 11 5A, 10 4Q, 9 4A
1Q VDD NC NC 6Q
3 2 1 20 19
1A 4, 2Q 5, NC 6, 2A 7, 3Q 8
18 6A, 17 NC, 16 NC, 15 5Q, 14 5A
9 10 11 12 13
3A GND NC 4A 4Q
4051
X4 1, X6 2, X 3, X7 4, X5 5, EN 6, VEE 7, GND 8
16 VDD, 15 X2, 14 X1, 13 X0, 12 X3, 11 S0, 10 S1, 9 S2
X5 X4 NC VDD X2
X 4, X7 5, NC 6, X5 7, EN 8
18 X1, 17 X0, 16 NC, 15 X3, 14 S0
VEE GND NC B2 S1
4052
2X0 1, 2X2 2, 2X 3, 2X3 4, 2X1 5, EN 6, VEE 7, GND 8
16 VDD, 15 1X2, 14 1X1, 13 1X, 12 1X0, 11 1X3, 10 S0, 9 S1
2X2 2X0 NC VDD 1X2
2X 4, 2X3 5, NC 6, 2X1 7, EN 8
18 1X1, 17 1X, 16 NC, 15 1X0, 14 1X3
VEE GND NC S1 S0
4053
2X1 1, 2X0 2, 3X1 3, 3X 4, 3X0 5, EN 6, VEE 7, GND 8
16 VDD, 15 2X, 14 1X, 13 1X1, 12 1X0, 11 S1, 10 S2, 9 S3
2X0 2X1 NC VDD 2X
3X1 4, 3X 5, NC 6, 3X0 7, EN 8
16 1X, 17 1X1, 16 NC, 15 1X0, 14 S1
VEE GND NC S3 S2
4054
STR4 1, FRM1 2, Q4 3, Q3 4, Q2 5, Q1 6, VEE 7, GND 8
16 VDD, 15 D4, 14 STR3, 13 D3, 12 STR2, 11 D2, 10 STR1, 9 D1
FRM1 STR4 NC VDD D4
Q4 4, Q3 5, NC 6, Q2 7, Q1 8
16 STR3, 17 D3, 16 NC, 15 STR2, 14 D2
VEE GND NC D1 STR1
4055
FRM0 1, D2 2, D1 3, D3 4, D0 5, FRM1 6, VEE 7, GND 8
16 VDD, 15 f, 14 g, 13 e, 12 d, 11 c, 10 b, 9 a
D2 FRM0 NC VDD f
D1 4, D3 5, NC 6, D0 7, FRM1 8
18 g, 17 e, 16 NC, 15 d, 14 c
VEE GND NC a b
4056
STR 1, D2 2, D1 3, D3 4, D0 5, FRM 6, VEE 7, GND 8
16 VDD, 15 f, 14 g, 13 e, 12 d, 11 c, 10 b, 9 a
D2 STR NC VDD f
D1 4, D3 5, NC 6, D0 7, FRM 8
18 g, 17 e, 16 NC, 15 d, 14 c
VEE GND NC a b
4059
CLK 1, ENL 2, J1 3, J2 4, J3 5, J4 6, J16 7, J15 8, J14 9, J13 10, S2 11, GND 12
24 VDD, 23 Q, 22 J5, 21 J6, 20 J7, 19 J8, 18 J9, 17 J10, 16 J11, 15 J12, 14 S0, 13 S1
4060
Q12 1, Q13 2, Q14 3, Q6 4, Q5 5, Q7 6, Q4 7, GND 8
16 VDD, 15 Q10, 14 Q8, 13 Q9, 12 CLR, 11 CLK1, 10 CLK0, 9 CLK0
4062
CLK 1, D 2, RCLK 3, REC 4, CLK2 5, 6, CL20 7, GND 8
16 VDD, 15, 14, 13 CM, 12 Q, 11 CLK1, 10 CL10, 9
VDD, CLK, CM, Q, Q, RC, CLK1, CL10, REC, CLK2, CL20, GND
4063
B3 1, E(A<B) 2, E(A=B) 3, E(A>B) 4, Q(A>B) 5, Q(A=B) 6, Q(A<B) 7, GND 8
16 VDD, 15 A3, 14 B2, 13 A2, 12 A1, 11 B1, 10 A0, 9 B0
E(A<B) B3 NC VDD A3
E(A=B) 4, E(A>B) 5, NC 6, Q(A>B) 7, Q(A=B) 8
18 A2, 17 B2, 16 NC, 15 A1, 14 B1
Q(A<B) GND NC B0 A0


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4078
Q(NC) 1, A 2, B 3, C 4, D 5, NC 6, GND 7
14 VDD, 13 Q̄, 12 H, 11 G, 10 F, 9 E, 8 NC
4078
A 3, Q 2, NC 1, VDD 20, Q̄ 19
B 4, NC 5, C 6, NC 7, D 8
18 H, 17 NC, 16 G, 15 NC, 14 NC
9 NC, 10 GND, 11 NC, 12 NC, 13 E
4081
1B 1, 1A 2, 1Q 3, 2Q 4, 2A 5, 2B 6, GND 7
14 VDD, 13 4B, 12 4A, 11 4Q, 10 3Q, 9 3A, 8 3B
4081
1A 3, 1B 2, NC 1, VDD 20, 4B 19
1Q 4, NC 5, 2Q 6, NC 7, 2A 8
18 4A, 17 NC, 16 4Q, 15 NC, 14 3Q
9 2B, 10 GND, 11 NC, 12 3B, 13 3A
4082
1Q 1, 1A 2, 1B 3, 1C 4, 1D 5, NC 6, GND 7
14 VDD, 13 2Q, 12 2A, 11 2B, 10 2C, 9 2D, 8 NC
4082
1A 3, 1Q 2, NC 1, VDD 20, 2Q 19
1B 4, NC 5, 1C 6, NC 7, 1D 8
18 2A, 17 NC, 16 2B, 15 NC, 14 2C
9 NC, 10 GND, 11 NC, 12 NC, 13 2D
4085
1A 1, 1B 2, 1Q̄ 3, 2Q̄ 4, 2A 5, 2B 6, GND 7
14 VDD, 13 1C, 12 1D, 11 2E, 10 1E, 9 2C, 8 2D
4085
1B 3, 1A 2, NC 1, VDD 20, 1C 19
1Q̄ 4, NC 5, 2Q̄ 6, NC 7, 2A 8
18 1D, 17 NC, 16 2E, 15 NC, 14 1E
9 2B, 10 GND, 11 NC, 12 2D, 13 2C
4086
A 1, B 2, Q̄ 3, NC 4, C 5, D 6, GND 7
14 VDD, 13 E, 12 F, 11 Ī, 10 J, 9 G, 8 H
4086
B 3, A 2, NC 1, VDD 20, E 19
Q̄ 4, NC 5, NC 6, NC 7, C 8
18 F, 17 NC, 16 Ī, 15 NC, 14 J
9 D, 10 GND, 11 NC, 12 H, 13 G
4089
Q15 1, C 2, D 3, S15 4, TC̄ 5, CASCO 6, INH OUT 7, GND 8
16 VDD, 15 B, 14 A, 13 R, 12 CASCI, 11 INH IN, 10 STR, 9 CLK
4089
C 3, Q15 2, NC 1, VDD 20, B 19
D 4, S15 5, NC 6, TC̄ 7, CASCD 8
18 A, 17 R, 16 NC, 15 CASCI, 14 INH IN
9 INH OUT, 10 GND, 11 NC, 12 CLK, 13 STR
4093
1A 1, 1B 2, 1Q̄ 3, 2Q̄ 4, 2B 5, 2A 6, GND 7
14 VDD, 13 4A, 12 4B, 11 4Q̄, 10 3Q̄, 9 3B, 8 3A
4093
1B 3, 1A 2, NC 1, VDD 20, 4A 19
1Q̄ 4, NC 5, 2Q̄ 6, NC 7, 2B 8
18 4B, 17 NC, 16 4Q̄, 15 NC, 14 3Q̄
9 2A, 10 GND, 11 NC, 12 3A, 13 3B
4094
STR 1, DS 2, CLK 3, Q0 4, Q1 5, Q2 6, Q3 7, GND 8
16 VDD, 15 EN0, 14 Q4, 13 Q5, 12 Q6, 11 Q7, 10 QS', 9 QS'
4094
D8 3, STR 2, NC 1, VDD 20, EN0 19
CLK 4, Q0 5, NC 6, Q1 7, Q2 8
18 Q4, 17 Q5, 16 NC, 15 Q6, 14 Q7
9 Q3, 10 GND, 11 NC, 12 QS', 13 QS
4095
NC 1, R 2, J1 3, J2 4, J3 5, Q̄ 6, GND 7
14 VDD, 13 S, 12 CLK, 11 K1, 10 K2, 9 K3, 8 Q
4095
R 3, NC 2, NC 1, VDD 20, S 19
J1 4, NC 5, J2 6, NC 7, J3 8
18 CLK, 17 NC, 16 K1, 15 NC, 14 K2
9 Q̄, 10 GND, 11 NC, 12 Q, 13 K3
4096
NC 1, R 2, J1 3, J2 4, J̄3 5, Q̄ 6, GND 7
14 VDD, 13 S, 12 CLK, 11 K1, 10 K2, 9 K̄3, 8 Q
4096
R 3, NC 2, NC 1, VDD 20, S 19
J1 4, NC 5, J2 6, NC 7, J̄3 8
18 CLK, 17 NC, 16 K1, 15 NC, 14 K2
9 Q̄, 10 GND, 11 NC, 12 Q, 13 K̄3

4097

X	1	24	VDD
X7	2	23	Y0
X6	3	22	Y1
X5	4	21	Y2
X4	5	20	Y3
X3	6	19	Y4
X2	7	16	Y5
X1	6	17	Y
X0	9	16	Y6
S0	10	15	Y7
S1	11	14	S2
GND	12	13	$\overline{EN}$

4098

1Cext	1	16	VDD
1RCext	2	15	2Cext
$\overline{1R}$	3	14	2RCext
1TR+	4	13	$\overline{2R}$
$\overline{1TR-}$	5	12	2TR+
1Q	6	11	$\overline{2TR-}$
$\overline{1Q}$	7	10	2Q
GND	8	9	$\overline{2Q}$

4099

Q7	1	16	VDD
R	2	15	Q6
D	3	14	Q5
$\overline{EN}$	4	13	Q4
A0	5	12	Q3
A1	6	11	Q2
A2	7	10	Q1
GND	8	9	Q0

4099 (20-pin)

Pin	Name
1	NC
2	Q7
3	R
4	D
5	$\overline{EN}$
6	NC
7	A0
8	A1
9	A2
10	GND
11	NC
12	Q0
13	Q1
14	Q2
15	Q3
16	NC
17	Q4
18	Q5
19	Q6
20	VDD

4104

VCC	1	16	VDD
$\overline{Q0}$	2	15	EN
Q0	3	14	$\overline{Q4}$
D0	4	13	Q4
D1	5	12	D4
Q1	6	11	D3
$\overline{Q1}$	7	10	Q3
GND	8	9	$\overline{Q3}$

4346

1I/O	1	16	VDD
1O/I	2	15	1C
2O/I	3	14	4C
2I/O	4	13	4D/I
2C	5	12	4I/O
3C	6	11	3I/O
$\overline{EN}$	7	10	3O/I
GND	8	9	VEE

4351

X4	1	20	VDD
X6	2	19	X2
NC	3	16	X1
X	4	17	X0
X7	5	16	X3
X5	6	15	S0
$\overline{EN1}$	7	14	NC
EN2	8	13	S1
VEE	9	12	S2
GND	10	11	$\overline{ENL}$

4352

2X0	1	20	VDD
2X2	2	19	1X2
NC	3	18	1X1
2X	4	17	1X
2X3	5	16	1X0
2X1	6	15	1X3
$\overline{EN1}$	7	14	NC
EN2	8	13	S0
VEE	9	12	S1
GND	10	11	$\overline{ENL}$

4353

2X1	1	20	VDD
2X0	2	19	2X
NC	3	18	1X
3X1	4	17	1X1
2X	5	16	1X1
3X0	6	15	S1
$\overline{EN1}$	7	14	NC
EN2	8	13	S2
$\overline{VEE}$	9	12	$\overline{S3}$
GND	10	11	$\overline{ENL}$

4402

1A	1	16	VDD
1B	2	15	2D
1C	3	14	2C
$\overline{1D}$	4	13	2B
1SOURCE(P)	5	12	2A
1DRAIN(P)	6	11	2DRAIN(P)
1DRAIN(N)	7	10	2DRAIN(N)
GND	8	9	2SOURCE(N)

4412

1A	1	16	VDD
1B	2	15	2D
1C	3	14	2C
1D	4	13	2B
1SDURCE (P)	5	12	2A
1DRAIN (P)	6	11	2DRAIN (P)
1DRAIN (N)	7	10	2DRAIN (N)
GND	8	9	2SOURCE (N)

4415

CLK	1	16	VDD
R	2	15	$\overline{INH}$
SA	3	14	QA
SB	4	13	QB
SC	5	12	QC
SD	6	11	QD
$\overline{STR1}$	7	10	DIS
GND	6	9	STR2

4426

CLK	1	16	VDD
$\overline{CEN}$	2	15	R
DSP IN	3	14	Q2
DSP OUT	4	13	c
CY0	5	12	b
f	8	11	e
g	7	10	a
GND	8	9	d

4426 (20-pin)

Pin	Name
1	NC
2	CLK
3	$\overline{CEN}$
4	DSP IN
5	DSP OUT
6	NC
7	CY0
8	f
9	g
10	GND
11	NC
12	d
13	a
14	e
15	b
16	NC
17	c
18	Q2
19	R
20	VDD

4428

4	1	14	VDD
2	2	13	3
0	3	12	1
7	4	11	B
5	5	10	C
6	6	9	STR
GND	7	8	A

4433

CLK	1	16	VDD
CEN	2	15	R
$\overline{RBI}$	3	14	LT
RBO	4	13	c
CYO	5	12	b
f	8	11	e
g	7	10	a
GND	8	9	d

4433 (20-pin)

Pin	Name
1	NC
2	CLK
3	CEN
4	$\overline{RBI}$
5	RBO
6	NC
7	CY0
6	f
9	g
10	GND
11	NC
12	d
13	a
14	e
15	b
16	NC
17	c
18	LT
19	R
20	VDD

4441

NC	1	14	VDD
1A	2	13	4A
$\overline{1Q}$	3	12	$\overline{4Q}$
NC	4	11	NC
2A	5	10	3A
$\overline{2Q}$	6	9	$\overline{3Q}$
GND	7	8	NC

4449

VDD	1	16	VD0
$\overline{1Q}$	2	15	$\overline{6Q}$
1A	3	14	6A
$\overline{2Q}$	4	13	NC
2A	5	12	$\overline{5Q}$
$\overline{3Q}$	6	11	5A
3A	7	10	$\overline{4Q}$
GND	8	9	4A

4490

AE	1	16	VDD
BQ	2	15	AQ
CE	3	14	BE
DQ	4	13	CQ
EE	5	12	DE
FQ	6	11	EQ
OSC IN	7	10	FE
GND	8	9	OSC DUT

4500

CHIP RESET	1	16	VDD
WRITE	2	15	RR
DATA	3	14	OSC OUT
I3	4	13	OSC IN
I2	5	12	FLAG JMP
I1	6	11	FLAG RTN
I0	7	10	FLAG 0
GND	8	9	FLAG F

4501

1A	1	16	VDD
1B	2	15	3Q
1C	3	14	$\overline{3Q}$
1D	4	13	$\overline{1Q}$
2A	5	12	3A
2B	6	11	3B
2C	7	10	$\overline{2Q}$
GND	8	9	2D

4502

D0	1	16	VDD
$\overline{Q0}$	2	15	D3
D1	3	14	$\overline{Q3}$
$\overline{EN}$	4	13	D4
$\overline{Q1}$	5	12	INH
D2	6	11	$\overline{Q4}$
$\overline{Q2}$	7	10	D5
GND	8	9	$\overline{Q5}$

4502 (PLCC)

1	NC
2	D0
3	$\overline{Q0}$
4	D1
5	$\overline{EN}$
6	NC
7	$\overline{Q1}$
8	D2
9	$\overline{Q2}$
10	GND
11	NC
12	$\overline{Q5}$
13	D6
14	$\overline{Q4}$
15	INH
16	NC
17	D4
18	$\overline{Q3}$
19	D3
20	VDD

4503

$\overline{EN1}$	1	16	VDD
D0	2	15	$\overline{EN2}$
Q0	3	14	D5
D1	4	13	Q5
Q1	5	12	D4
D2	6	11	Q4
Q2	7	10	D3
GND	8	9	Q3

4503 (PLCC)

1	NC
2	$\overline{EN1}$
3	1Q
4	Q0
5	D1
6	NC
7	Q1
8	D2
9	Q2
10	GND
11	NC
12	Q3
13	D3
14	Q4
15	D4
16	NC
17	Q5
18	D5
19	$\overline{EN2}$
20	VDD

4504

VCC	1	16	VDD
1Q	2	15	6Q
1A	3	14	6A
2Q	4	13	MODE
2A	5	12	5Q
3Q	6	11	5A
3A	7	10	4Q
GND	8	9	4A

4505

A0	1	14	VDD
A1	2	13	D
A2	3	12	A5
A3	4	11	A4
STR	5	10	Q
CE1	6	9	R/$\overline{W}$
GND	7	8	CE2

4506

1A	1	16	VDD
1B	2	15	1Q
1C	3	14	EN0
1D	4	13	2E
1E	5	12	2A
1INH	6	11	2B
2Q	7	10	2C
GND	8	9	2D

4507

1A	1	14	VDD
1B	2	13	4A
1Q	3	12	4B
2Q	4	11	4Q
2B	5	10	3Q
2A	6	9	$\overline{3B}$
GND	7	8	3A

4508

1MR	1	24	VDD
1STR	2	23	2Q3
1DIS	3	22	2D3
1D0	4	21	2Q2
1Q0	5	20	2D2
1D1	6	19	2Q1
1Q1	7	18	2D1
1D2	8	17	2Q0
1Q2	9	16	2D0
1D3	10	15	2DIS
1Q3	11	14	2STR
GND	12	13	2MR

4510

LD	1	16	VDD
Q3	2	15	CLK
D3	3	14	Q2
D1	4	13	D2
$\overline{CEN}$	5	12	D1
Q1	6	11	Q1
$\overline{TC}$	7	10	SEL U/$\overline{D}$
GND	8	9	MR

4510 (PLCC)

1	NC
2	LD
3	Q3
4	D3
5	D1
6	NC
7	$\overline{CEN}$
8	Q1
9	$\overline{TC}$
10	GND
11	NC
12	MR
13	SEL U/$\overline{D}$
14	Q1
15	D1
16	NC
17	D2
18	Q2
19	CLK
20	VDD

4511

D1	1	16	VDD
D2	2	15	f
$\overline{LT}$	3	14	g
$\overline{BI}$	4	13	a
$\overline{ENL}$	5	12	b
D3	6	11	c
D0	7	10	d
GND	8	9	e

4511 (PLCC)

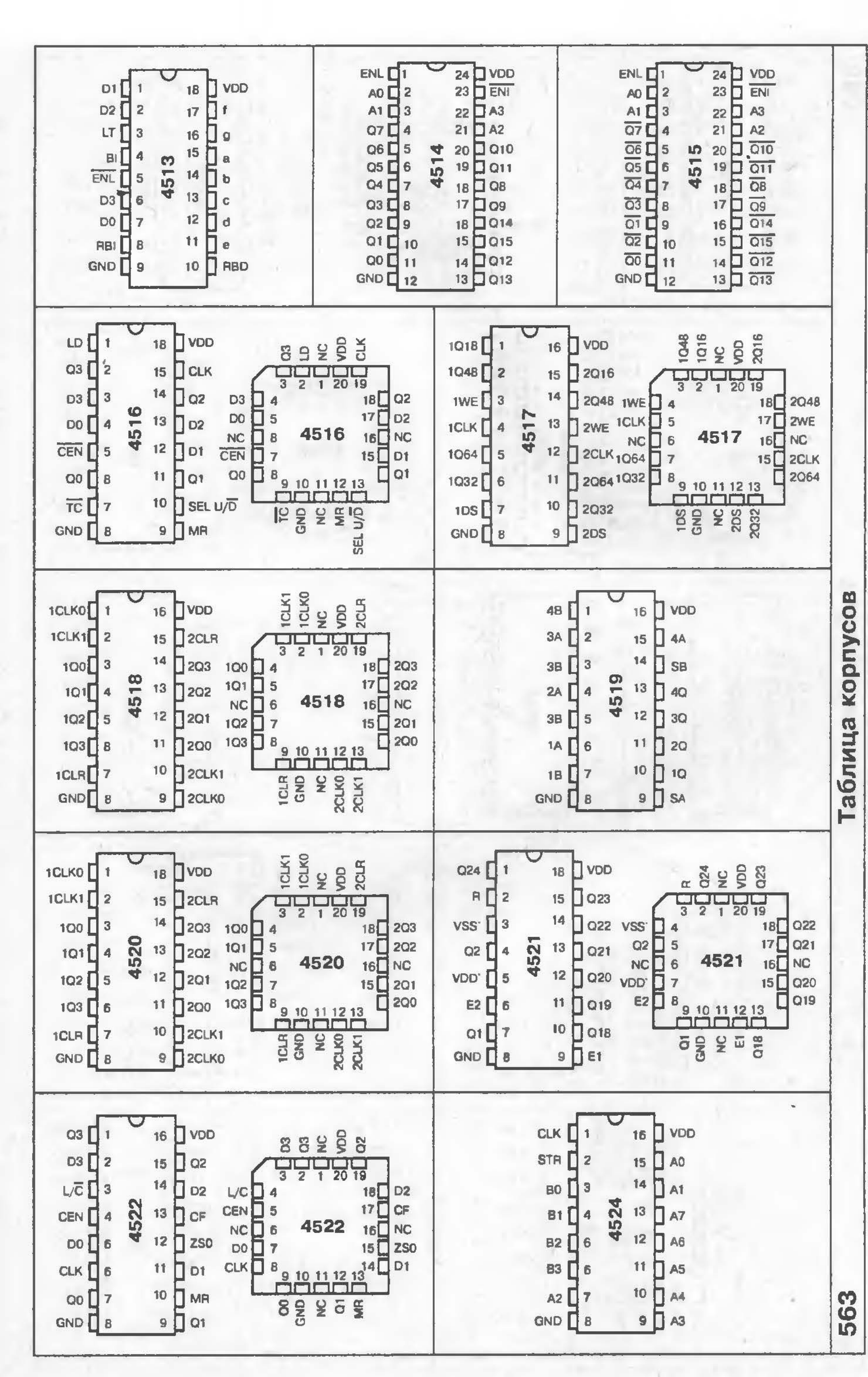
1	NC
2	D1
3	D2
4	$\overline{LT}$
5	$\overline{BI}$
6	NC
7	$\overline{ENL}$
8	D3
9	D0
10	GND
11	NC
12	e
13	d
14	c
15	b
16	NC
17	a
18	g
19	f
20	VCC

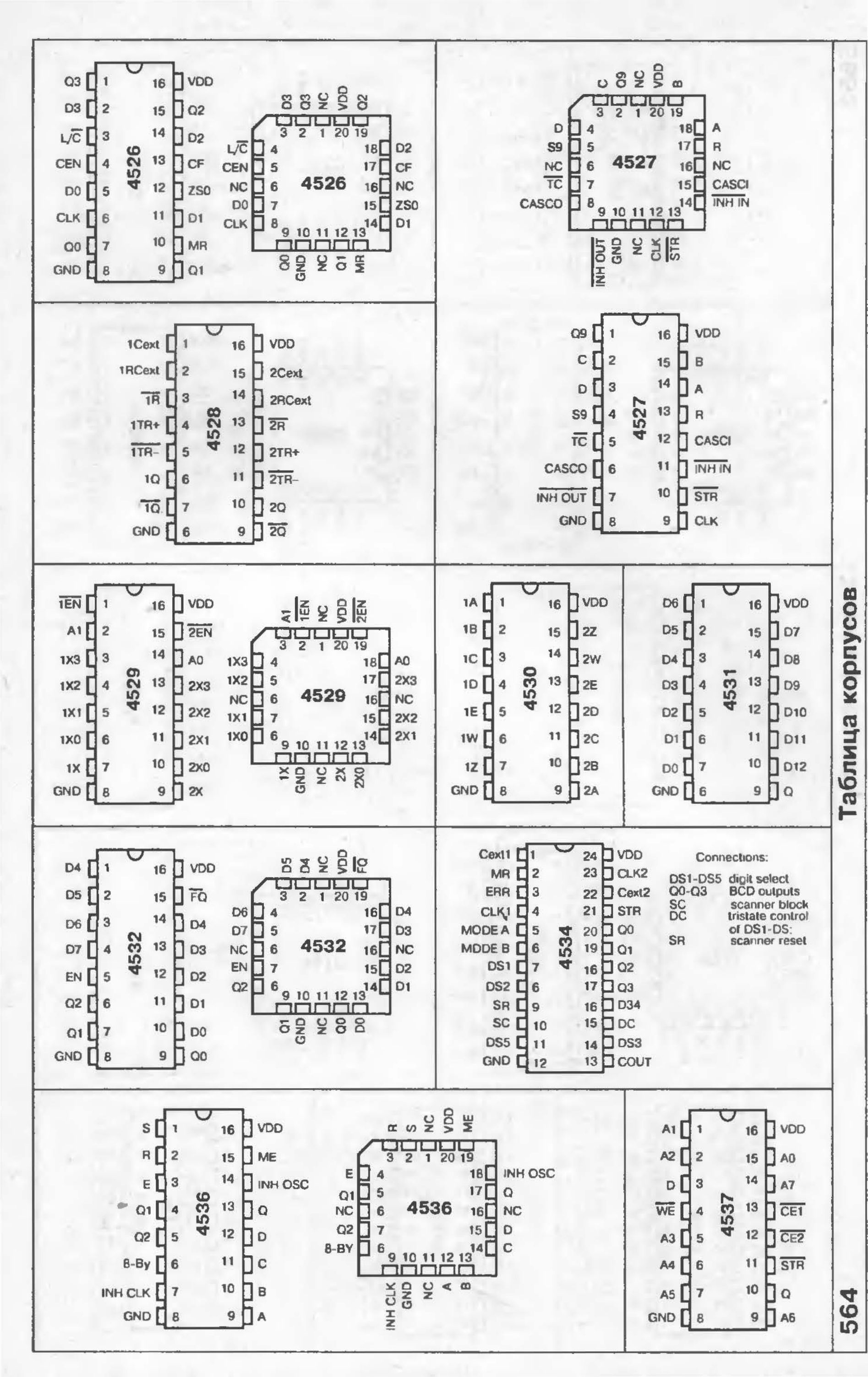
4512

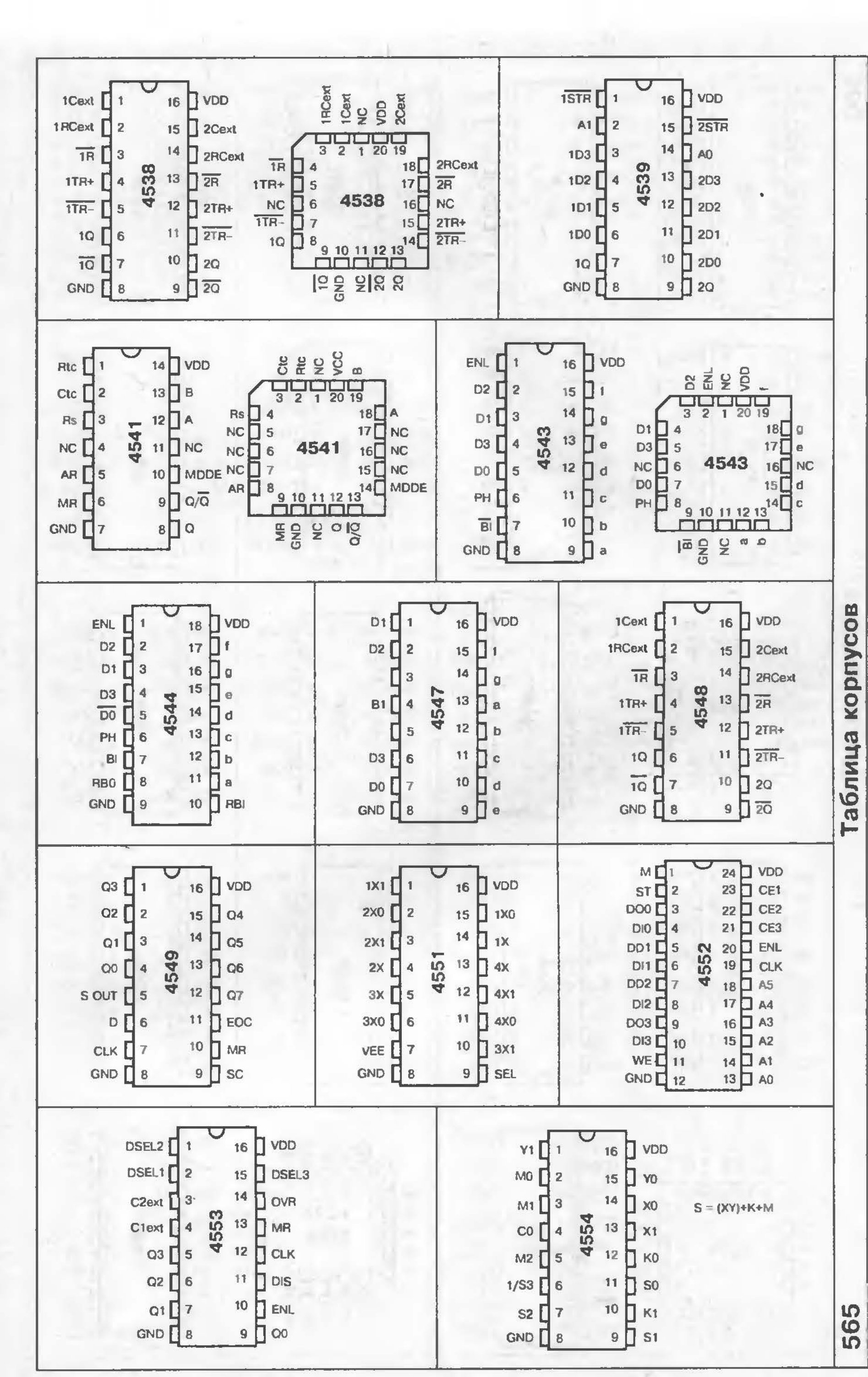
D0	1	16	VDD
D1	2	15	$\overline{EN}$
D2	3	14	Q
D3	4	13	A2
D4	5	12	A1
D5	6	11	A0
D6	7	10	$\overline{INH}$
GND	8	9	D7

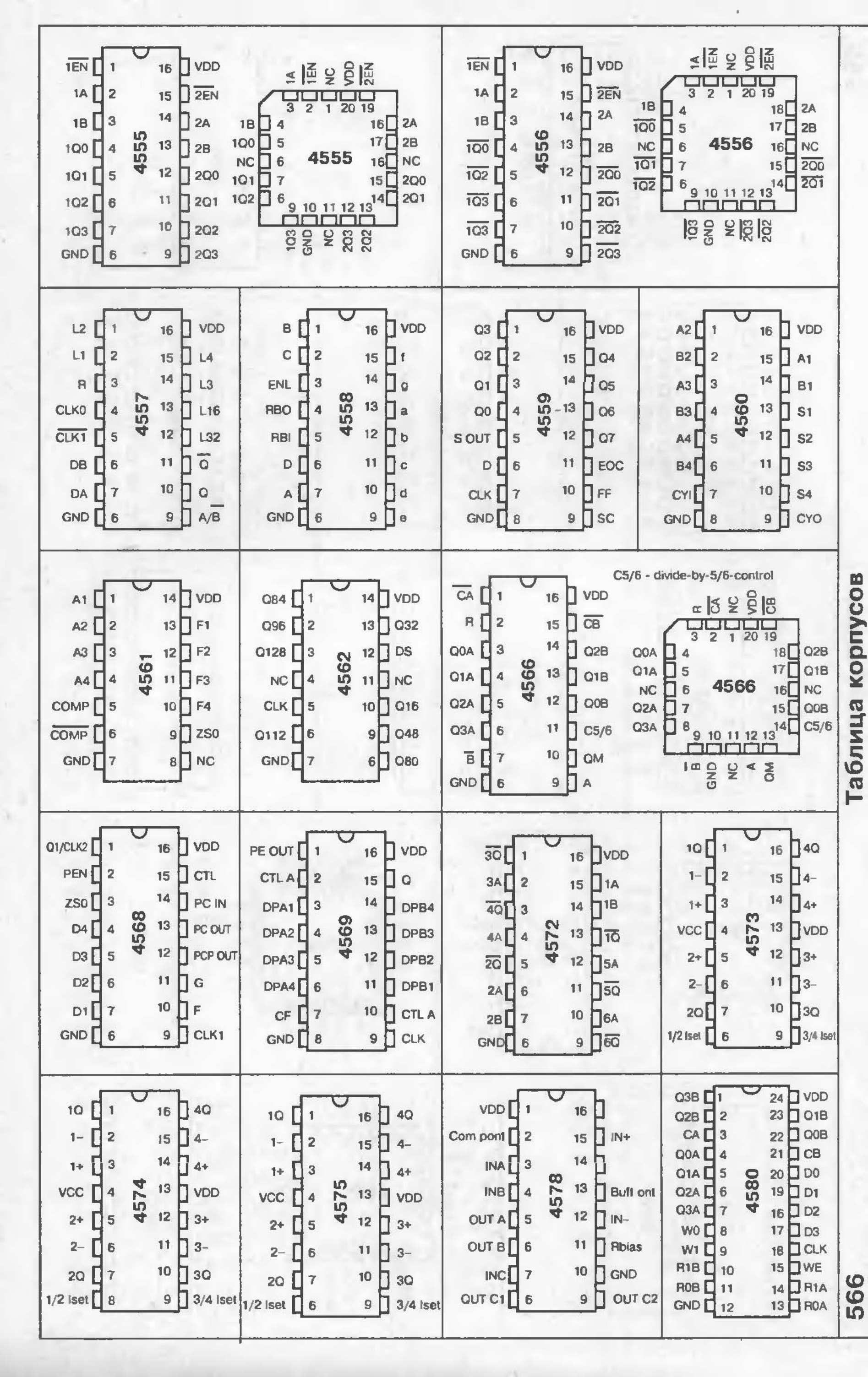
4512 (PLCC)

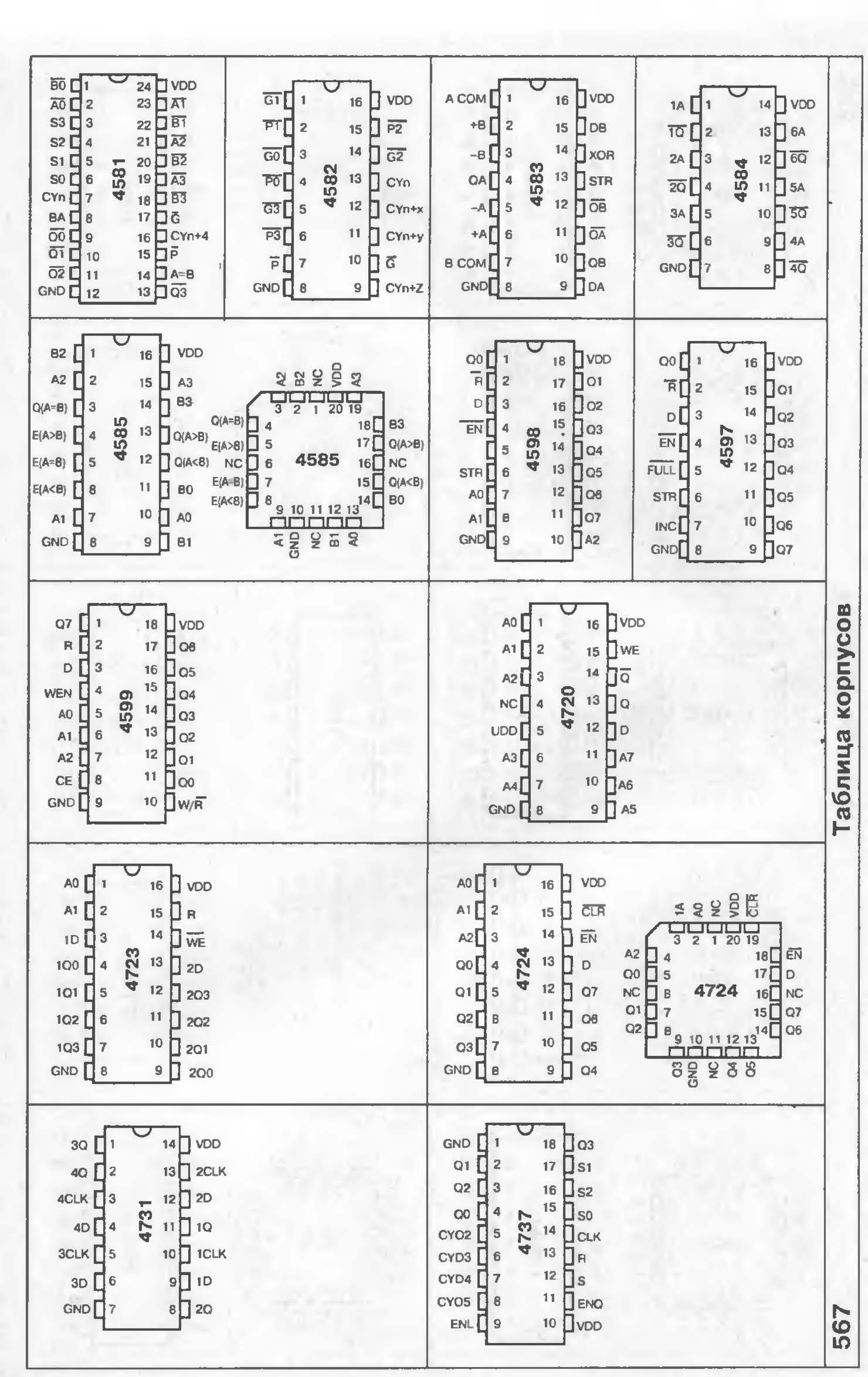
1	NC
2	D0
3	D1
4	D2
5	D3
6	NC
7	D4
8	D5
9	D6
10	GND
11	NC
12	D7
13	$\overline{INH}$
14	A0
15	A1
16	NC
17	A2
18	Q
19	$\overline{EN}$
20	VDD

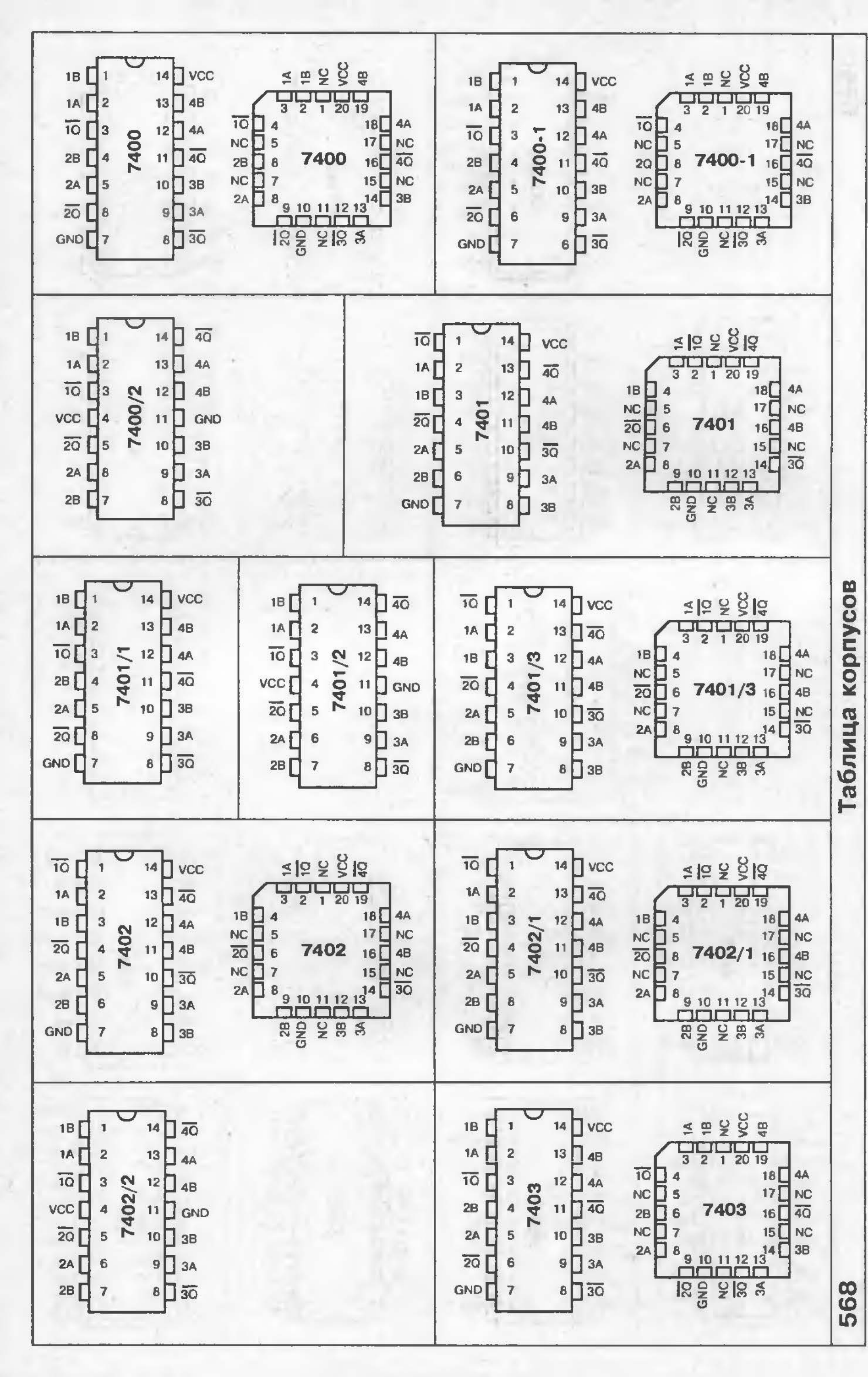

4513
D1 1, D2 2, LT 3, BI 4, ENL 5, D3 6, D0 7, RBI 8, GND 9
RBD 10, e 11, d 12, c 13, b 14, a 15, g 16, f 17, VDD 18
4514
ENL 1, A0 2, A1 3, Q7 4, Q6 5, Q5 6, Q4 7, Q3 8, Q2 9, Q1 10, Q0 11, GND 12
Q13 13, Q12 14, Q15 15, Q14 18, Q9 17, Q8 18, Q11 19, Q10 20, A2 21, A3 22, ENI 23, VDD 24
4515
ENL 1, A0 2, A1 3, Q7 4, Q6 5, Q5 6, Q4 7, Q3 8, Q1 9, Q2 10, Q0 11, GND 12
Q13 13, Q12 14, Q15 15, Q14 16, Q9 17, Q8 18, Q11 19, Q10 20, A2 21, A3 22, ENI 23, VDD 24
4516
LD 1, Q3 2, D3 3, D0 4, CEN 5, Q0 8, TC 7, GND 8
MR 9, SEL U/D 10, Q1 11, D1 12, D2 13, Q2 14, CLK 15, VDD 18
4516
Q3 3, LD 2, NC 1, VDD 20, CLK 19
D3 4, D0 5, NC 8, CEN 7, Q0 8
Q2 18, D2 17, NC 16, D1 15, Q1
TC 9, GND 10, NC 11, MR 12, SEL U/D 13
4517
1Q16 1, 1Q48 2, 1WE 3, 1CLK 4, 1Q64 5, 1Q32 6, 1DS 7, GND 8
2DS 9, 2Q32 10, 2Q64 11, 2CLK 12, 2WE 13, 2Q48 14, 2Q16 15, VDD 16
4517
1Q48 3, 1Q16 2, NC 1, VDD 20, 2Q16 19
1WE 4, 1CLK 5, NC 6, 1Q64 7, 1Q32 8
2Q48 18, 2WE 17, NC 16, 2CLK 15, 2Q64
1DS 9, GND 10, NC 11, 2DS 12, 2Q32 13
4518
1CLK0 1, 1CLK1 2, 1Q0 3, 1Q1 4, 1Q2 5, 1Q3 8, 1CLR 7, GND 8
2CLK0 9, 2CLK1 10, 2Q0 11, 2Q1 12, 2Q2 13, 2Q3 14, 2CLR 15, VDD 16
4518
1CLK1 3, 1CLK0 2, NC 1, VDD 20, 2CLR 19
1Q0 4, 1Q1 5, NC 6, 1Q2 7, 1Q3 8
2Q3 18, 2Q2 17, NC 16, 2Q1 15, 2Q0
1CLR 9, GND 10, NC 11, 2CLK0 12, 2CLK1 13
4519
4B 1, 3A 2, 3B 3, 2A 4, 3B 5, 1A 6, 1B 7, GND 8
SA 9, 1Q 10, 2Q 11, 3Q 12, 4Q 13, SB 14, 4A 15, VDD 16
4520
1CLK0 1, 1CLK1 2, 1Q0 3, 1Q1 4, 1Q2 5, 1Q3 6, 1CLR 7, GND 8
2CLK0 9, 2CLK1 10, 2Q0 11, 2Q1 12, 2Q2 13, 2Q3 14, 2CLR 15, VDD 18
4520
1CLK1 3, 1CLK0 2, NC 1, VDD 20, 2CLR 19
1Q0 4, 1Q1 5, NC 6, 1Q2 7, 1Q3 8
2Q3 18, 2Q2 17, NC 16, 2Q1 15, 2Q0
1CLR 9, GND 10, NC 11, 2CLK0 12, 2CLK1 13
4521
Q24 1, R 2, VSS' 3, Q2 4, VDD' 5, E2 6, Q1 7, GND 8
E1 9, Q18 10, Q19 11, Q20 12, Q21 13, Q22 14, Q23 15, VDD 18
4521
R 3, Q24 2, NC 1, VDD 20, Q23 19
VSS' 4, Q2 5, NC 6, VDD' 7, E2 8
Q22 18, Q21 17, NC 16, Q20 15, Q19
Q1 9, GND 10, NC 11, E1 12, Q18 13
4522
Q3 1, D3 2, L/C 3, CEN 4, D0 6, CLK 6, Q0 7, GND 8
Q1 9, MR 10, D1 11, ZS0 12, CF 13, D2 14, Q2 15, VDD 16
4522
D3 3, Q3 2, NC 1, VDD 20, Q2 19
L/C 4, CEN 5, NC 6, D0 7, CLK 8
D2 18, CF 17, NC 16, ZS0 15, D1 14
Q0 9, GND 10, NC 11, Q1 12, MR 13
4524
CLK 1, STR 2, B0 3, B1 4, B2 6, B3 6, A2 7, GND 8
A3 9, A4 10, A5 11, A6 12, A7 13, A1 14, A0 15, VDD 16

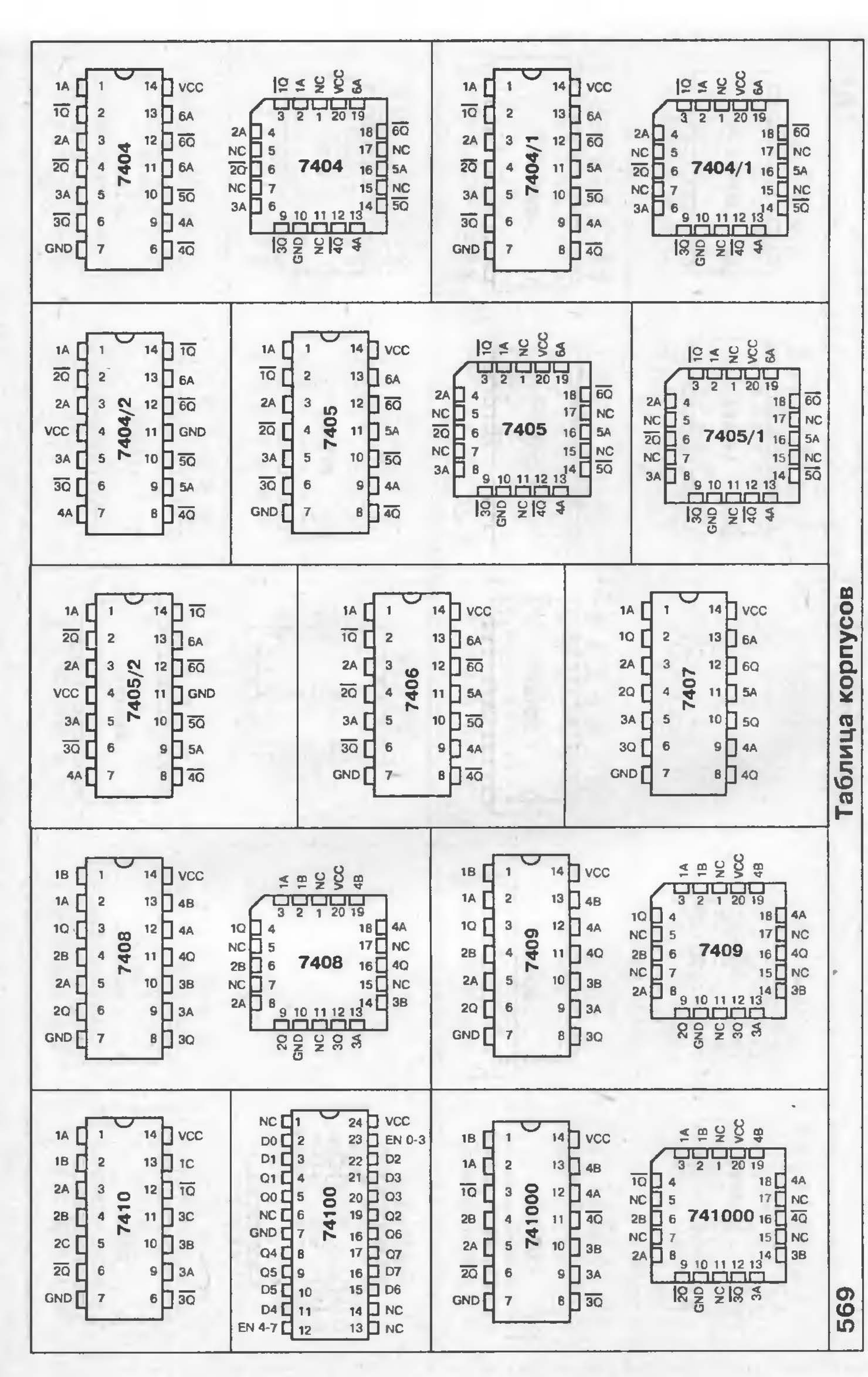

4526
Q3 1 16 VDD
D3 2 15 Q2
L/C 3 14 D2
CEN 4 13 CF
D0 5 12 ZS0
CLK 6 11 D1
Q0 7 10 MR
GND 8 9 Q1
4526
D3 Q3 NC VDD Q2
3 2 1 20 19
L/C 4 18 D2
CEN 5 17 CF
NC 6 16 NC
D0 7 15 ZS0
CLK 8 14 D1
9 10 11 12 13
Q0 GND NC Q1 MR
4527
C Q9 NC VDD B
3 2 1 20 19
D 4 18 A
S9 5 17 R
NC 6 16 NC
TC 7 15 CASCI
CASCO 8 14 INH IN
9 10 11 12 13
INH OUT GND NC CLK STR
4527
Q9 1 16 VDD
C 2 15 B
D 3 14 A
S9 4 13 R
TC 5 12 CASCI
CASCO 6 11 INH IN
INH OUT 7 10 STR
GND 8 9 CLK
4528
1Cext 1 16 VDD
1RCext 2 15 2Cext
1R 3 14 2RCext
1TR+ 4 13 2R
1TR– 5 12 2TR+
1Q 6 11 2TR–
1Q 7 10 2Q
GND 6 9 2Q
4529
1EN 1 16 VDD
A1 2 15 2EN
1X3 3 14 A0
1X2 4 13 2X3
1X1 5 12 2X2
1X0 6 11 2X1
1X 7 10 2X0
GND 8 9 2X
4529
A1 1EN NC VDD 2EN
3 2 1 20 19
1X3 4 18 A0
1X2 5 17 2X3
NC 6 16 NC
1X1 7 15 2X2
1X0 6 14 2X1
9 10 11 12 13
1X GND NC 2X 2X0
4530
1A 1 16 VDD
1B 2 15 2Z
1C 3 14 2W
1D 4 13 2E
1E 5 12 2D
1W 6 11 2C
1Z 7 10 2B
GND 8 9 2A
4531
D6 1 16 VDD
D5 2 15 D7
D4 3 14 D8
D3 4 13 D9
D2 5 12 D10
D1 6 11 D11
D0 7 10 D12
GND 6 9 Q
4532
D4 1 16 VDD
D5 2 15 FQ
D6 3 14 D4
D7 4 13 D3
EN 5 12 D2
Q2 6 11 D1
Q1 7 10 D0
GND 8 9 Q0
4532
D5 D4 NC VDD FQ
3 2 1 20 19
D6 4 16 D4
D7 5 17 D3
NC 6 16 NC
EN 7 15 D2
Q2 6 14 D1
9 10 11 12 13
Q1 GND NC Q0 D0
4534
Cext1 1 24 VDD
MR 2 23 CLK2
ERR 3 22 Cext2
CLK1 4 21 STR
MODE A 5 20 Q0
MODE B 6 19 Q1
DS1 7 16 Q2
DS2 6 17 Q3
SR 9 16 D34
SC 10 15 DC
DS5 11 14 DS3
GND 12 13 COUT
Connections:
DS1-DS5 digit select
Q0-Q3 BCD outputs
SC scanner block
DC tristate control of DS1-DS:
SR scanner reset
4536
S 1 16 VDD
R 2 15 ME
E 3 14 INH OSC
Q1 4 13 Q
Q2 5 12 D
8-By 6 11 C
INH CLK 7 10 B
GND 8 9 A
4536
R S NC VDD ME
3 2 1 20 19
E 4 18 INH OSC
Q1 5 17 Q
NC 6 16 NC
Q2 7 15 D
8-BY 6 14 C
9 10 11 12 13
INH CLK GND NC A B
4537
A1 1 16 VDD
A2 2 15 A0
D 3 14 A7
WE 4 13 CE1
A3 5 12 CE2
A4 6 11 STR
A5 7 10 Q
GND 8 9 A6

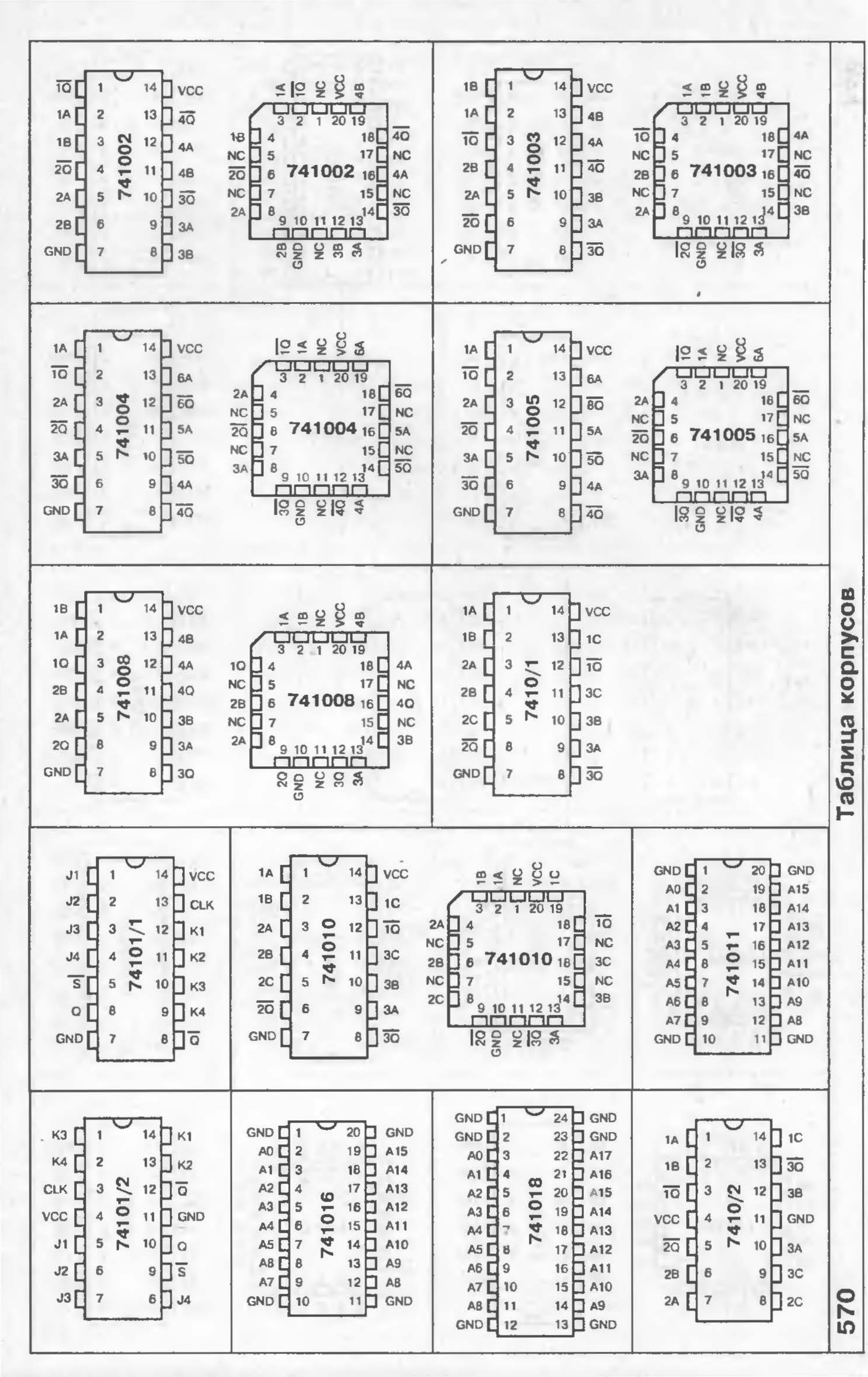

4538
1Cext 1, 1RCext 2, 1R 3, 1TR+ 4, 1TR- 5, 1Q 6, 1Q 7, GND 8
16 VDD, 15 2Cext, 14 2RCext, 13 2R, 12 2TR+, 11 2TR-, 10 2Q, 9 2Q
4538
1RCext 3, 1Cext 2, NC 1, VDD 20, 2Cext 19
1R 4, 1TR+ 5, NC 6, 1TR- 7, 1Q 8
18 2RCext, 17 2R, 16 NC, 15 2TR+, 14 2TR-
1Q 9, GND 10, NC 11, 2Q 12, 2Q 13
4539
1STR 1, A1 2, 1D3 3, 1D2 4, 1D1 5, 1D0 6, 1Q 7, GND 8
16 VDD, 15 2STR, 14 A0, 13 2D3, 12 2D2, 11 2D1, 10 2D0, 9 2Q
4541
Rtc 1, Ctc 2, Rs 3, NC 4, AR 5, MR 6, GND 7
14 VDD, 13 B, 12 A, 11 NC, 10 MDDE, 9 Q/Q, 8 Q
4541
Ctc 3, Rtc 2, NC 1, VCC 20, B 19
Rs 4, NC 5, NC 6, NC 7, AR 8
18 A, 17 NC, 16 NC, 15 NC, 14 MDDE
MR 9, GND 10, NC 11, Q 12, Q/Q 13
4543
ENL 1, D2 2, D1 3, D3 4, D0 5, PH 6, BI 7, GND 8
16 VDD, 15 f, 14 g, 13 e, 12 d, 11 c, 10 b, 9 a
4543
D2 3, ENL 2, NC 1, VDD 20, f 19
D1 4, D3 5, NC 6, D0 7, PH 8
18 g, 17 e, 16 NC, 15 d, 14 c
BI 9, GND 10, NC 11, a 12, b 13
4544
ENL 1, D2 2, D1 3, D3 4, D0 5, PH 6, BI 7, RB0 8, GND 9
18 VDD, 17 f, 16 g, 15 e, 14 d, 13 c, 12 b, 11 a, 10 RBI
4547
D1 1, D2 2, 3, B1 4, 5, D3 6, D0 7, GND 8
16 VDD, 15 f, 14 g, 13 a, 12 b, 11 c, 10 d, 9 e
4548
1Cext 1, 1RCext 2, 1R 3, 1TR+ 4, 1TR- 5, 1Q 6, 1Q 7, GND 8
16 VDD, 15 2Cext, 14 2RCext, 13 2R, 12 2TR+, 11 2TR-, 10 2Q, 9 2Q
4549
Q3 1, Q2 2, Q1 3, Q0 4, S OUT 5, D 6, CLK 7, GND 8
16 VDD, 15 Q4, 14 Q5, 13 Q6, 12 Q7, 11 EOC, 10 MR, 9 SC
4551
1X1 1, 2X0 2, 2X1 3, 2X 4, 3X 5, 3X0 6, VEE 7, GND 8
16 VDD, 15 1X0, 14 1X, 13 4X, 12 4X1, 11 4X0, 10 3X1, 9 SEL
4552
M 1, ST 2, DO0 3, DI0 4, DO1 5, DI1 6, DO2 7, DI2 8, DO3 9, DI3 10, WE 11, GND 12
24 VDD, 23 CE1, 22 CE2, 21 CE3, 20 ENL, 19 CLK, 18 A5, 17 A4, 16 A3, 15 A2, 14 A1, 13 A0
4553
DSEL2 1, DSEL1 2, C2ext 3, C1ext 4, Q3 5, Q2 6, Q1 7, GND 8
16 VDD, 15 DSEL3, 14 OVR, 13 MR, 12 CLK, 11 DIS, 10 ENL, 9 Q0
4554
Y1 1, M0 2, M1 3, C0 4, M2 5, 1/S3 6, S2 7, GND 8
16 VDD, 15 Y0, 14 X0, 13 X1, 12 K0, 11 S0, 10 K1, 9 S1
S = (XY)+K+M

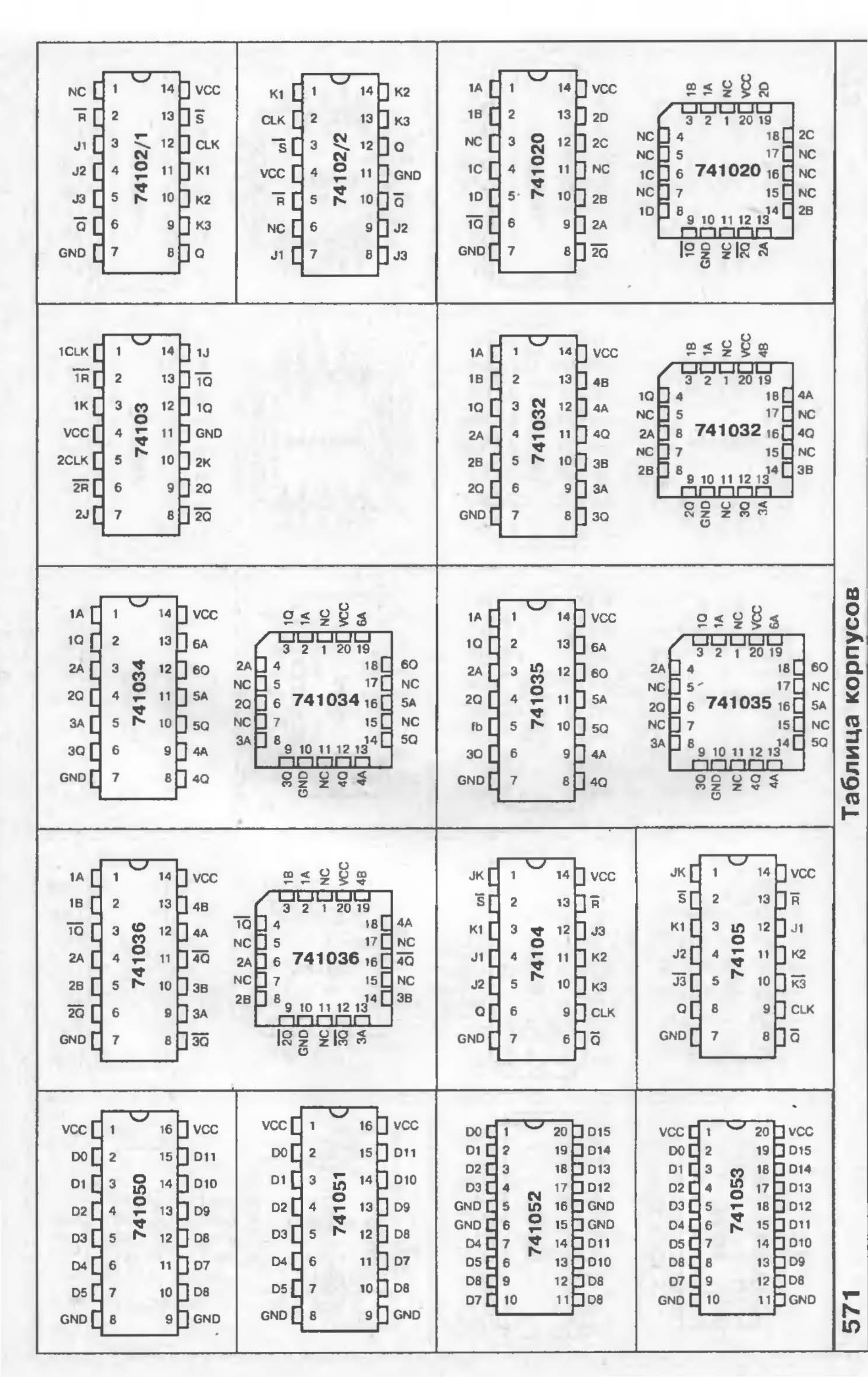

4555
1EN 1 16 VDD
1A 2 15 2EN
1B 3 14 2A
1Q0 4 13 2B
1Q1 5 12 2Q0
1Q2 6 11 2Q1
1Q3 7 10 2Q2
GND 6 9 2Q3
4555
1A 1EN NC VDD 2EN
3 2 1 20 19
1B 4 16 2A
1Q0 5 17 2B
NC 6 16 NC
1Q1 7 15 2Q0
1Q2 6 14 2Q1
9 10 11 12 13
1Q3 GND NC 2Q3 2Q2
4556
1EN 1 16 VDD
1A 2 15 2EN
1B 3 14 2A
1Q0 4 13 2B
1Q2 5 12 2Q0
1Q3 6 11 2Q1
1Q3 7 10 2Q2
GND 6 9 2Q3
4556
1A 1EN NC VDD 2EN
3 2 1 20 19
1B 4 18 2A
1Q0 5 17 2B
NC 6 16 NC
1Q1 7 15 2Q0
1Q2 6 14 2Q1
9 10 11 12 13
1Q3 GND NC 2Q3 2Q2
4557
L2 1 16 VDD
L1 2 15 L4
R 3 14 L3
CLK0 4 13 L16
CLK1 5 12 L32
DB 6 11 Q
DA 7 10 Q
GND 6 9 A/B
4558
B 1 16 VDD
C 2 15 f
ENL 3 14 g
RBO 4 13 a
RBI 5 12 b
D 6 11 c
A 7 10 d
GND 6 9 e
4559
Q3 1 16 VDD
Q2 2 15 Q4
Q1 3 14 Q5
Q0 4 13 Q6
S OUT 5 12 Q7
D 6 11 EOC
CLK 7 10 FF
GND 8 9 SC
4560
A2 1 16 VDD
B2 2 15 A1
A3 3 14 B1
B3 4 13 S1
A4 5 12 S2
B4 6 11 S3
CYI 7 10 S4
GND 8 9 CYO
4561
A1 1 14 VDD
A2 2 13 F1
A3 3 12 F2
A4 4 11 F3
COMP 5 10 F4
COMP 6 9 ZS0
GND 7 8 NC
4562
Q84 1 14 VDD
Q96 2 13 Q32
Q128 3 12 DS
NC 4 11 NC
CLK 5 10 Q16
Q112 6 9 Q48
GND 7 6 Q80
4566
CA 1 16 VDD
R 2 15 CB
Q0A 3 14 Q2B
Q1A 4 13 Q1B
Q2A 5 12 Q0B
Q3A 6 11 C5/6
B 7 10 QM
GND 6 9 A
C5/6 - divide-by-5/6-control
4566
R CA NC VDD CB
3 2 1 20 19
Q0A 4 18 Q2B
Q1A 5 17 Q1B
NC 6 16 NC
Q2A 7 15 Q0B
Q3A 8 14 C5/6
9 10 11 12 13
B GND NC A QM
4568
Q1/CLK2 1 16 VDD
PEN 2 15 CTL
ZS0 3 14 PC IN
D4 4 13 PC OUT
D3 5 12 PCP OUT
D2 6 11 G
D1 7 10 F
GND 6 9 CLK1
4569
PE OUT 1 16 VDD
CTL A 2 15 Q
DPA1 3 14 DPB4
DPA2 4 13 DPB3
DPA3 5 12 DPB2
DPA4 6 11 DPB1
CF 7 10 CTL A
GND 8 9 CLK
4572
3Q 1 16 VDD
3A 2 15 1A
4Q 3 14 1B
4A 4 13 1Q
2Q 5 12 5A
2A 6 11 5Q
2B 7 10 6A
GND 6 9 6Q
4573
1Q 1 16 4Q
1– 2 15 4–
1+ 3 14 4+
VCC 4 13 VDD
2+ 5 12 3+
2– 6 11 3–
2Q 7 10 3Q
1/2 Iset 6 9 3/4 Iset
4574
1Q 1 16 4Q
1– 2 15 4–
1+ 3 14 4+
VCC 4 13 VDD
2+ 5 12 3+
2– 6 11 3–
2Q 7 10 3Q
1/2 Iset 8 9 3/4 Iset
4575
1Q 1 16 4Q
1– 2 15 4–
1+ 3 14 4+
VCC 4 13 VDD
2+ 5 12 3+
2– 6 11 3–
2Q 7 10 3Q
1/2 Iset 6 9 3/4 Iset
4578
VDD 1 16
Com pont 2 15 IN+
INA 3 14
INB 4 13 Buff ont
OUT A 5 12 IN–
OUT B 6 11 Rbias
INC 7 10 GND
OUT C1 6 9 OUT C2
4580
Q3B 1 24 VDD
Q2B 2 23 Q1B
CA 3 22 Q0B
Q0A 4 21 CB
Q1A 5 20 D0
Q2A 6 19 D1
Q3A 7 16 D2
W0 8 17 D3
W1 9 18 CLK
R1B 10 15 WE
R0B 11 14 R1A
GND 12 13 R0A

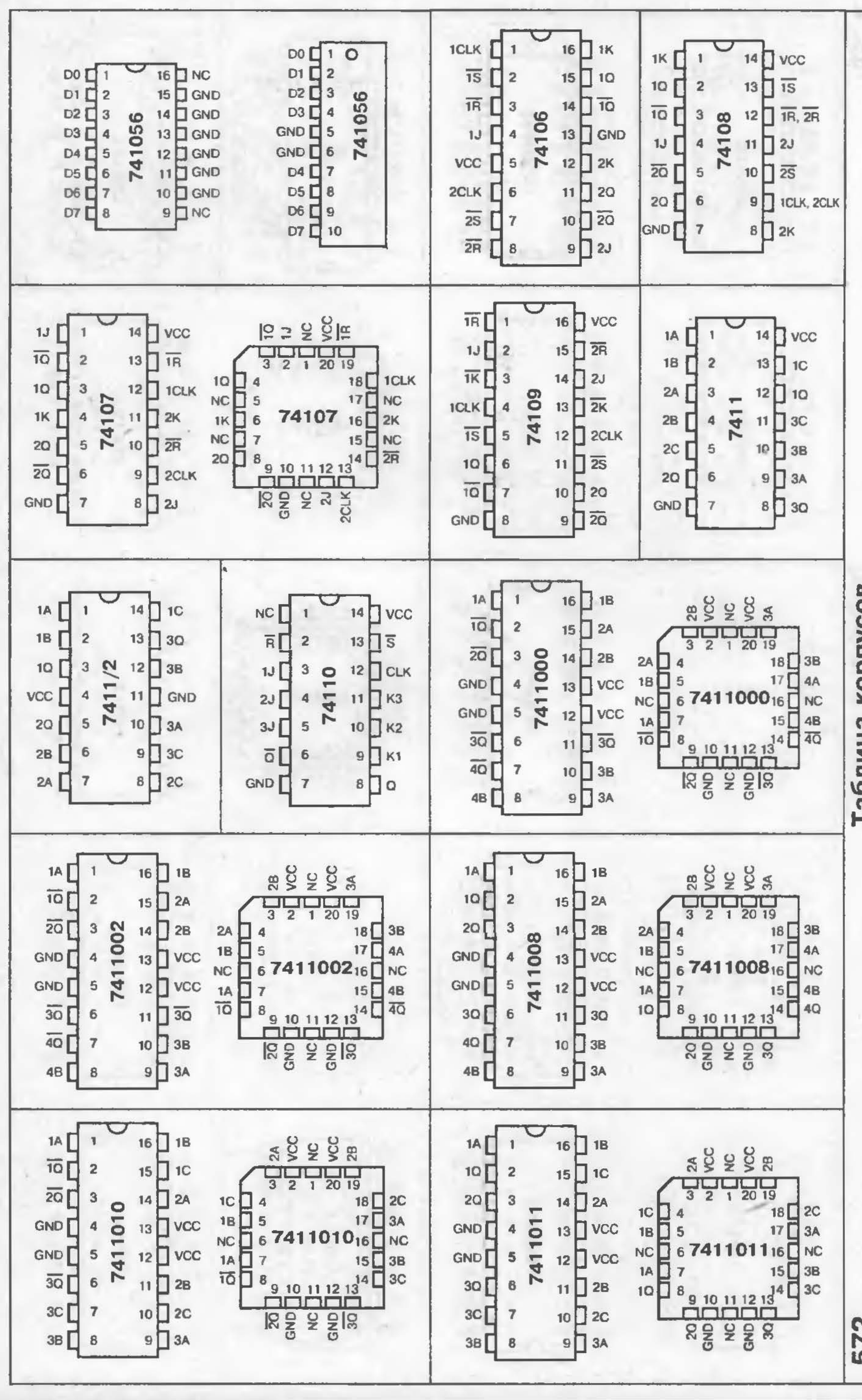

4581
B0 1, A0 2, S3 3, S2 4, S1 5, S0 6, CYn 7, BA 8, O0 9, O1 10, O2 11, GND 12
24 VDD, 23 A1, 22 B1, 21 A2, 20 B2, 19 A3, 18 B3, 17 G, 16 CYn+4, 15 P, 14 A=B, 13 O3
4582
G1 1, P1 2, G0 3, P0 4, G3 5, P3 6, P 7, GND 8
16 VDD, 15 P2, 14 G2, 13 CYn, 12 CYn+x, 11 CYn+y, 10 G, 9 CYn+Z
4583
A COM 1, +B 2, −B 3, QA 4, −A 5, +A 6, B COM 7, GND 8
16 VDD, 15 DB, 14 XOR, 13 STR, 12 QB, 11 QA, 10 QB, 9 DA
4584
1A 1, 1Q 2, 2A 3, 2Q 4, 3A 5, 3Q 6, GND 7
14 VDD, 13 6A, 12 6Q, 11 5A, 10 5Q, 9 4A, 8 4Q
4585
B2 1, A2 2, Q(A=B) 3, E(A>B) 4, E(A=B) 5, E(A<B) 6, A1 7, GND 8
16 VDD, 15 A3, 14 B3, 13 Q(A>B), 12 Q(A<B), 11 B0, 10 A0, 9 B1
4585
A2 3, B2 2, NC 1, VDD 20, A3 19
Q(A=B) 4, E(A>B) 5, NC 6, E(A=B) 7, E(A<B) 8
18 B3, 17 Q(A>B), 16 NC, 15 Q(A<B), 14 B0
A1 9, GND 10, NC 11, B1 12, A0 13
4598
Q0 1, R 2, D 3, EN 4, 5, STR 6, A0 7, A1 8, GND 9
18 VDD, 17 O1, 16 O2, 15 O3, 14 O4, 13 O5, 12 O6, 11 O7, 10 A2
4597
Q0 1, R 2, D 3, EN 4, FULL 5, STR 6, INC 7, GND 8
16 VDD, 15 Q1, 14 Q2, 13 Q3, 12 Q4, 11 Q5, 10 Q6, 9 Q7
4599
Q7 1, R 2, D 3, WEN 4, A0 5, A1 6, A2 7, CE 8, GND 9
18 VDD, 17 Q6, 16 Q5, 15 Q4, 14 Q3, 13 Q2, 12 Q1, 11 Q0, 10 W/R
4720
A0 1, A1 2, A2 3, NC 4, UDD 5, A3 6, A4 7, GND 8
16 VDD, 15 WE, 14 Q, 13 Q, 12 D, 11 A7, 10 A6, 9 A5
4723
A0 1, A1 2, 1D 3, 1Q0 4, 1Q1 5, 1Q2 6, 1Q3 7, GND 8
16 VDD, 15 R, 14 WE, 13 2D, 12 2Q3, 11 2Q2, 10 2Q1, 9 2Q0
4724
A0 1, A1 2, A2 3, Q0 4, Q1 5, Q2 6, Q3 7, GND 8
16 VDD, 15 CLR, 14 EN, 13 D, 12 Q7, 11 Q6, 10 Q5, 9 Q4
4724
1A 3, A0 2, NC 1, VDD 20, CLR 19
A2 4, Q0 5, NC 6, Q1 7, Q2 8
18 EN, 17 D, 16 NC, 15 Q7, 14 Q6
Q3 9, GND 10, NC 11, Q4 12, Q5 13
4731
3Q 1, 4Q 2, 4CLK 3, 4D 4, 3CLK 5, 3D 6, GND 7
14 VDD, 13 2CLK, 12 2D, 11 1Q, 10 1CLK, 9 1D, 8 2Q
4737
GND 1, Q1 2, Q2 3, Q0 4, CYO2 5, CYD3 6, CYD4 7, CYO5 8, ENL 9
18 Q3, 17 S1, 16 S2, 15 S0, 14 CLK, 13 R, 12 S, 11 ENQ, 10 VDD

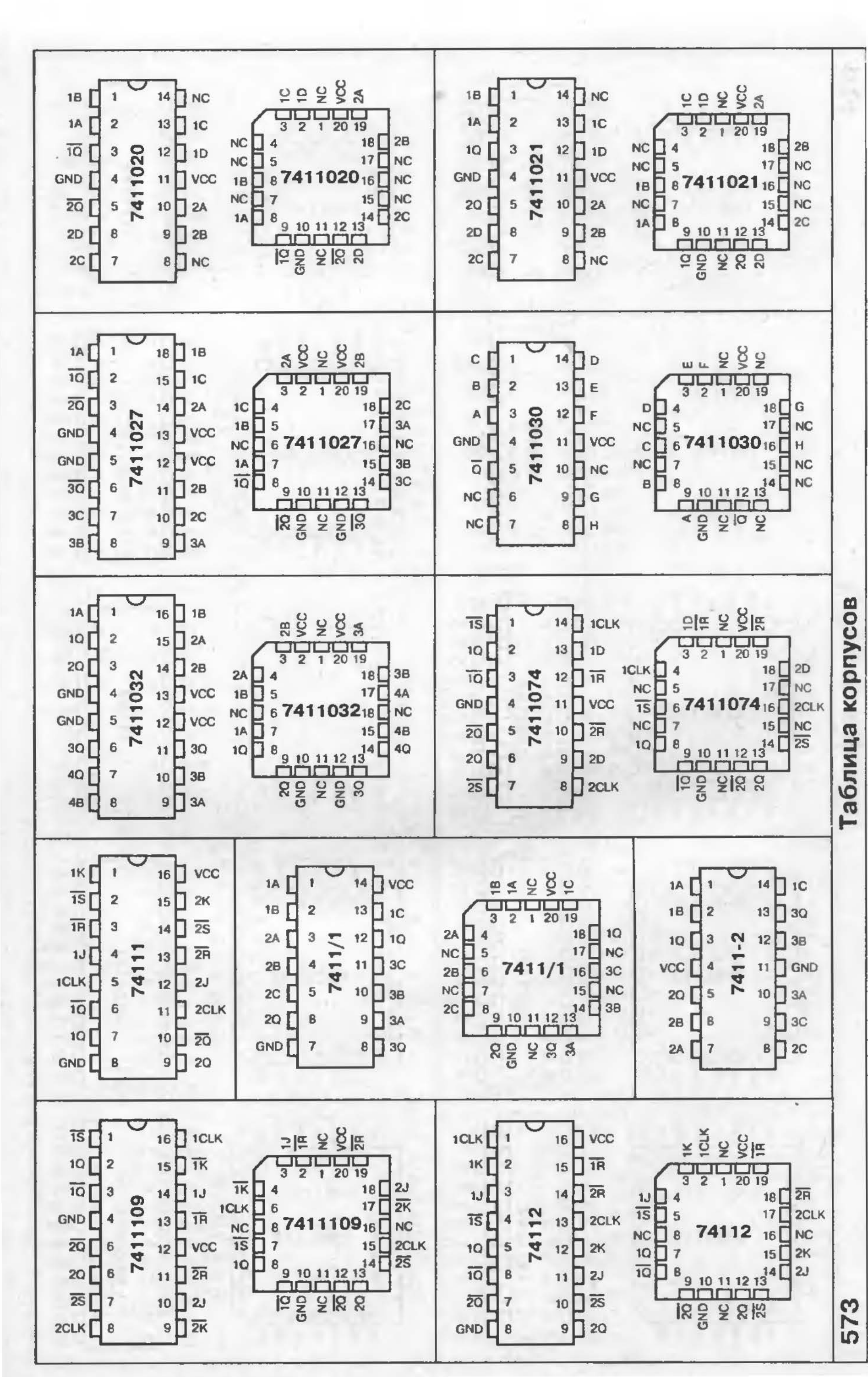

7400
7400
7400-1
7400-1
7400/2
7401
7401
7401/1
7401/2
7401/3
7401/3
7402
7402
7402/1
7402/1
7402/2
7403
7403

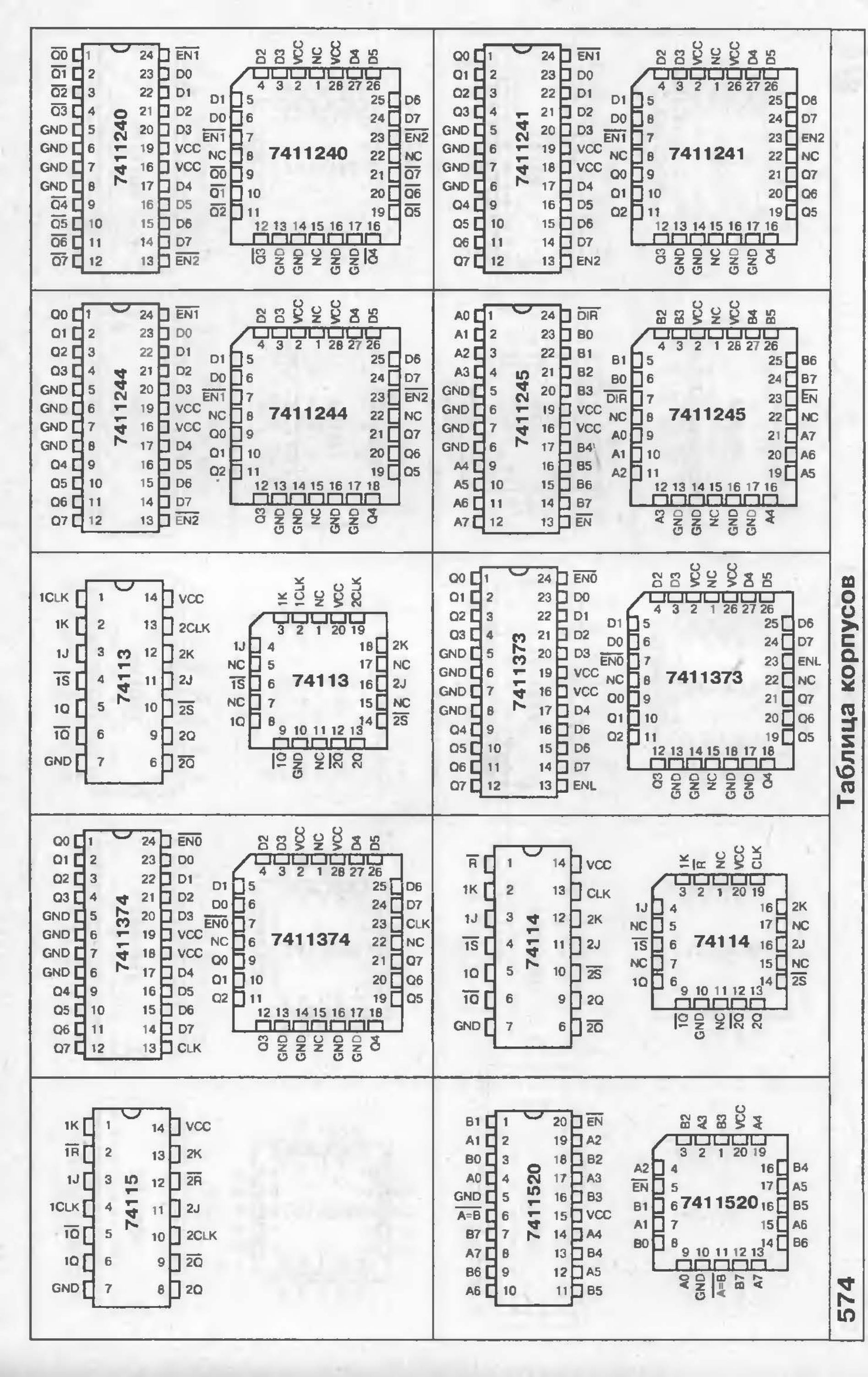

7404
7404/1
7404/2
7405
7405/1
7405/2
7406
7407
7408
7409
7410
74100
741000


741002
1Q 1A 1B 2Q 2A 2B GND 3B 3A 3Q 4B 4A 4Q VCC
741003
1B 1A 1Q 2B 2A 2Q GND 3Q 3A 3B 4Q 4A 4B VCC
741004
1A 1Q 2A 2Q 3A 3Q GND 4Q 4A 5Q 5A 6Q 6A VCC
741005
1A 1Q 2A 2Q 3A 3Q GND 4Q 4A 5Q 5A 6Q 6A VCC
741008
1B 1A 1Q 2B 2A 2Q GND 3Q 3A 3B 4Q 4A 4B VCC
7410/1
1A 1B 2A 2B 2C 2Q GND 3Q 3A 3B 3C 1Q 1C VCC
74101/1
J1 J2 J3 J4 S Q GND Q K4 K3 K2 K1 CLK VCC
741010
1A 1B 2A 2B 2C 2Q GND 3Q 3A 3B 3C 1Q 1C VCC
741011
GND A0 A1 A2 A3 A4 A5 A6 A7 GND GND A8 A9 A10 A11 A12 A13 A14 A15 GND
74101/2
K3 K4 CLK VCC J1 J2 J3 J4 S Q GND Q K2 K1
741016
GND A0 A1 A2 A3 A4 A5 A6 A7 GND GND A8 A9 A10 A11 A12 A13 A14 A15 GND
741018
GND GND A0 A1 A2 A3 A4 A5 A6 A7 A8 GND GND A9 A10 A11 A12 A13 A14 A15 A16 A17 GND GND
7410/2
1A 1B 1Q VCC 2Q 2B 2A 2C 3C 3A GND 3B 3Q 1C


74102/1: NC 1, R̄ 2, J1 3, J2 4, J3 5, Q̄ 6, GND 7, Q 8, K3 9, K2 10, K1 11, CLK 12, S̄ 13, VCC 14
74102/2: K1 1, CLK 2, S̄ 3, VCC 4, R̄ 5, NC 6, J1 7, J3 8, J2 9, Q̄ 10, GND 11, Q 12, K3 13, K2 14
741020: 1A 1, 1B 2, NC 3, 1C 4, 1D 5, 1Q̄ 6, GND 7, 2Q̄ 8, 2A 9, 2B 10, NC 11, 2C 12, 2D 13, VCC 14
741020: 1B 3, 1A 2, NC 1, VCC 20, 2D 19, NC 4, NC 5, 1C 6, NC 7, 1D 8, 2C 18, NC 17, NC 16, NC 15, 2B 14, 1Q̄ 9, GND 10, NC 11, 2Q̄ 12, 2A 13
74103: 1CLK 1, 1R̄ 2, 1K 3, VCC 4, 2CLK 5, 2R̄ 6, 2J 7, 2Q̄ 8, 2Q 9, 2K 10, GND 11, 1Q 12, 1Q̄ 13, 1J 14
741032: 1A 1, 1B 2, 1Q 3, 2A 4, 2B 5, 2Q 6, GND 7, 3Q 8, 3A 9, 3B 10, 4Q 11, 4A 12, 4B 13, VCC 14
741032: 1B 3, 1A 2, NC 1, VCC 20, 4B 19, 1Q 4, NC 5, 2A 8, NC 7, 2B 8, 4A 18, NC 17, 4Q 16, NC 15, 3B 14, 2Q 9, GND 10, NC 11, 3Q 12, 3A 13
741034: 1A 1, 1Q 2, 2A 3, 2Q 4, 3A 5, 3Q 6, GND 7, 4Q 8, 4A 9, 5Q 10, 5A 11, 6O 12, 6A 13, VCC 14
741034: 1Q 3, 1A 2, NC 1, VCC 20, 6A 19, 2A 4, NC 5, 2Q 6, NC 7, 3A 8, 6O 18, NC 17, 5A 16, NC 15, 5Q 14, 3Q 9, GND 10, NC 11, 4Q 12, 4A 13
741035: 1A 1, 1Q 2, 2A 3, 2Q 4, fb 5, 3O 6, GND 7, 4Q 8, 4A 9, 5Q 10, 5A 11, 6O 12, 6A 13, VCC 14
741035: 1O 3, 1A 2, NC 1, VCC 20, 6A 19, 2A 4, NC 5, 2Q 6, NC 7, 3A 8, 6O 18, NC 17, 5A 16, NC 15, 5Q 14, 3O 9, GND 10, NC 11, 4Q 12, 4A 13
741036: 1A 1, 1B 2, 1Q̄ 3, 2A 4, 2B 5, 2Q̄ 6, GND 7, 3Q̄ 8, 3A 9, 3B 10, 4Q̄ 11, 4A 12, 4B 13, VCC 14
741036: 1B 3, 1A 2, NC 1, VCC 20, 4B 19, 1Q̄ 4, NC 5, 2A 6, NC 7, 2B 8, 4A 18, NC 17, 4Q̄ 16, NC 15, 3B 14, 2Q̄ 9, GND 10, NC 11, 3Q̄ 12, 3A 13
74104: JK 1, S̄ 2, K1 3, J1 4, J2 5, Q 6, GND 7, Q̄ 6, CLK 9, K3 10, K2 11, J3 12, R̄ 13, VCC 14
74105: JK 1, S̄ 2, K1 3, J2 4, J̄3 5, Q 8, GND 7, Q̄ 8, CLK 9, K̄3 10, K2 11, J1 12, R̄ 13, VCC 14
741050: VCC 1, D0 2, D1 3, D2 4, D3 5, D4 6, D5 7, GND 8, GND 9, D8 10, D7 11, D8 12, D9 13, D10 14, D11 15, VCC 16
741051: VCC 1, D0 2, D1 3, D2 4, D3 5, D4 6, D5 7, GND 8, GND 9, D8 10, D7 11, D8 12, D9 13, D10 14, D11 15, VCC 16
741052: D0 1, D1 2, D2 3, D3 4, GND 5, GND 6, D4 7, D5 6, D8 9, D7 10, D8 11, D8 12, D10 13, D11 14, GND 15, GND 16, D12 17, D13 18, D14 19, D15 20
741053: VCC 1, D0 2, D1 3, D2 4, D3 5, D4 6, D5 7, D8 8, D7 9, GND 10, GND 11, D8 12, D9 13, D10 14, D11 15, D12 18, D13 17, D14 18, D15 19, VCC 20


741056: 1 D0, 2 D1, 3 D2, 4 D3, 5 D4, 6 D5, 7 D6, 8 D7, 9 NC, 10 GND, 11 GND, 12 GND, 13 GND, 14 GND, 15 GND, 16 NC
741056: D0 1, D1 2, D2 3, D3 4, GND 5, GND 6, D4 7, D5 8, D6 9, D7 10
74106: 1 1CLK, 2 $\overline{1S}$, 3 $\overline{1R}$, 4 1J, 5 VCC, 6 2CLK, 7 $\overline{2S}$, 8 $\overline{2R}$, 9 2J, 10 $\overline{2Q}$, 11 2Q, 12 2K, 13 GND, 14 $\overline{1Q}$, 15 1Q, 16 1K
74108: 1 1K, 2 1Q, 3 $\overline{1Q}$, 4 1J, 5 $\overline{2Q}$, 6 2Q, 7 GND, 8 2K, 9 1CLK, 2CLK, 10 $\overline{2S}$, 11 2J, 12 $\overline{1R}$, $\overline{2R}$, 13 $\overline{1S}$, 14 VCC
74107: 1 1J, 2 $\overline{1Q}$, 3 1Q, 4 1K, 5 2Q, 6 $\overline{2Q}$, 7 GND, 8 2J, 9 2CLK, 10 $\overline{2R}$, 11 2K, 12 1CLK, 13 $\overline{1R}$, 14 VCC
74107: 1 NC, 2 1J, 3 $\overline{1Q}$, 4 1Q, 5 NC, 6 1K, 7 NC, 8 2Q, 9 $\overline{2Q}$, 10 GND, 11 NC, 12 2J, 13 2CLK, 14 $\overline{2R}$, 15 NC, 16 2K, 17 NC, 18 1CLK, 19 $\overline{1R}$, 20 VCC
74109: 1 $\overline{1R}$, 2 1J, 3 $\overline{1K}$, 4 1CLK, 5 $\overline{1S}$, 6 1Q, 7 $\overline{1Q}$, 8 GND, 9 $\overline{2Q}$, 10 2Q, 11 $\overline{2S}$, 12 2CLK, 13 $\overline{2K}$, 14 2J, 15 $\overline{2R}$, 16 VCC
7411: 1 1A, 2 1B, 3 2A, 4 2B, 5 2C, 6 2Q, 7 GND, 8 3Q, 9 3A, 10 3B, 11 3C, 12 1Q, 13 1C, 14 VCC
7411/2: 1 1A, 2 1B, 3 1Q, 4 VCC, 5 2Q, 6 2B, 7 2A, 8 2C, 9 3C, 10 3A, 11 GND, 12 3B, 13 3Q, 14 1C
74110: 1 NC, 2 $\overline{R}$, 3 1J, 4 2J, 5 3J, 6 $\overline{Q}$, 7 GND, 8 Q, 9 K1, 10 K2, 11 K3, 12 CLK, 13 $\overline{S}$, 14 VCC
7411000: 1 1A, 2 $\overline{1Q}$, 3 $\overline{2Q}$, 4 GND, 5 GND, 6 $\overline{3Q}$, 7 $\overline{4Q}$, 8 4B, 9 3A, 10 3B, 11 $\overline{3Q}$, 12 VCC, 13 VCC, 14 2B, 15 2A, 16 1B
7411000: 1 NC, 2 VCC, 3 2B, 4 2A, 5 1B, 6 NC, 7 1A, 8 $\overline{1Q}$, 9 $\overline{2Q}$, 10 GND, 11 NC, 12 GND, 13 $\overline{3Q}$, 14 $\overline{4Q}$, 15 4B, 16 NC, 17 4A, 18 3B, 19 3A, 20 VCC
7411002: 1 1A, 2 $\overline{1Q}$, 3 $\overline{2Q}$, 4 GND, 5 GND, 6 $\overline{3Q}$, 7 $\overline{4Q}$, 8 4B, 9 3A, 10 3B, 11 $\overline{3Q}$, 12 VCC, 13 VCC, 14 2B, 15 2A, 16 1B
7411002: 1 NC, 2 VCC, 3 2B, 4 2A, 5 1B, 6 NC, 7 1A, 8 $\overline{1Q}$, 9 $\overline{2Q}$, 10 GND, 11 NC, 12 GND, 13 $\overline{3Q}$, 14 $\overline{4Q}$, 15 4B, 16 NC, 17 4A, 18 3B, 19 3A, 20 VCC
7411008: 1 1A, 2 1Q, 3 2Q, 4 GND, 5 GND, 6 3Q, 7 4Q, 8 4B, 9 3A, 10 3B, 11 3Q, 12 VCC, 13 VCC, 14 2B, 15 2A, 16 1B
7411008: 1 NC, 2 VCC, 3 2B, 4 2A, 5 1B, 6 NC, 7 1A, 8 1Q, 9 2Q, 10 GND, 11 NC, 12 GND, 13 3Q, 14 4Q, 15 4B, 16 NC, 17 4A, 18 3B, 19 3A, 20 VCC
7411010: 1 1A, 2 $\overline{1Q}$, 3 $\overline{2Q}$, 4 GND, 5 GND, 6 $\overline{3Q}$, 7 3C, 8 3B, 9 3A, 10 2C, 11 2B, 12 VCC, 13 VCC, 14 2A, 15 1C, 16 1B
7411010: 1 NC, 2 VCC, 3 2A, 4 1C, 5 1B, 6 NC, 7 1A, 8 $\overline{1Q}$, 9 $\overline{2Q}$, 10 GND, 11 NC, 12 GND, 13 $\overline{3Q}$, 14 3C, 15 3B, 16 NC, 17 3A, 18 2C, 19 2B, 20 VCC
7411011: 1 1A, 2 1Q, 3 2Q, 4 GND, 5 GND, 6 3Q, 7 3C, 8 3B, 9 3A, 10 2C, 11 2B, 12 VCC, 13 VCC, 14 2A, 15 1C, 16 1B
7411011: 1 NC, 2 VCC, 3 2A, 4 1C, 5 1B, 6 NC, 7 1A, 8 1Q, 9 2Q, 10 GND, 11 NC, 12 GND, 13 3Q, 14 3C, 15 3B, 16 NC, 17 3A, 18 2C, 19 2B, 20 VCC


7411020
7411021
7411027
7411030
7411032
7411074
74111
7411/1
7411-2
7411109
74112


7411240
7411241
7411244
7411245
74113
7411373
7411374
74114
74115
7411520

7411521

Pin	Signal	Pin	Signal
1	B1	20	$\overline{EN}$
2	A1	19	A2
3	B0	18	B2
4	A0	17	A3
5	GND	16	B3
6	$\overline{A=B}$	15	VCC
7	B7	14	A4
6	A7	13	B4
9	B6	12	A5
10	A6	11	B5

7411521 (PLCC)

Pin	Signal
3	B2
2	A3
1	B3
20	VCC
19	A4
4	A2
5	$\overline{EN}$
6	B1
7	A1
8	B0
18	B4
17	A5
16	B5
15	A6
14	B6
9	A0
10	GND
11	$\overline{A=B}$
12	B7
13	A7

7411533

Pin	Signal	Pin	Signal
1	$\overline{Q0}$	24	$\overline{ENO}$
2	$\overline{Q1}$	23	D0
3	$\overline{Q2}$	22	D1
4	$\overline{Q3}$	21	D2
5	GND	20	D3
6	GND	19	VCC
7	GND	18	VCC
8	GND	17	D4
9	$\overline{Q4}$	16	D5
10	$\overline{Q5}$	15	D6
11	$\overline{Q6}$	14	D7
12	$\overline{Q7}$	13	ENL

7411533 (PLCC)

Pin	Signal	Pin	Signal
4	D2	5	D1
3	D3	6	D0
2	VCC	7	$\overline{ENO}$
1	NC	8	NC
28	VCC	9	$\overline{Q0}$
27	D4	10	$\overline{Q1}$
26	D5	11	$\overline{Q2}$
25	D6	12	$\overline{Q3}$
24	D7	13	GND
23	ENL	14	GND
22	NC	15	NC
21	$\overline{Q7}$	16	GND
20	$\overline{Q6}$	17	GND
19	$\overline{Q5}$	18	$\overline{Q4}$

7411534

Pin	Signal	Pin	Signal
1	$\overline{Q0}$	24	$\overline{ENO}$
2	$\overline{Q1}$	23	D0
3	$\overline{Q2}$	22	D1
4	$\overline{Q3}$	21	D2
5	GND	20	D3
6	GND	19	VCC
7	GND	18	VCC
8	GND	17	D4
9	$\overline{Q4}$	16	D5
10	$\overline{Q5}$	15	D6
11	$\overline{Q6}$	14	D7
12	$\overline{Q7}$	13	CLK

7411534 (PLCC)

Pin	Signal	Pin	Signal
4	D2	5	D1
3	D3	6	D0
2	VCC	7	$\overline{END}$
1	NC	8	NC
28	VCC	9	$\overline{Q0}$
27	D4	10	$\overline{Q1}$
26	D5	11	$\overline{Q2}$
25	D6	12	$\overline{Q3}$
24	D7	13	GND
23	CLK	14	GND
22	NC	15	NC
21	$\overline{Q7}$	16	GND
20	$\overline{Q6}$	17	GND
19	$\overline{Q5}$	16	$\overline{Q4}$

74116

Pin	Signal	Pin	Signal
1	$\overline{1R}$	24	VCC
2	$\overline{1EN1}$	23	2Q4
3	$\overline{1EN2}$	22	2D4
4	1D1	21	2Q3
5	1Q1	20	2D3
6	1D2	19	2Q2
7	1Q2	16	2D2
8	1D3	17	2Q1
9	1Q3	16	2D1
10	1D4	15	$\overline{2EN2}$
11	1Q4	14	$\overline{2EN1}$
12	GND	13	$\overline{2R}$

7411620

Pin	Signal	Pin	Signal
1	A0	24	GAB
2	A1	23	B0
3	A2	22	B1
4	A3	21	B2
5	GND	20	B3
8	GND	19	VCC
7	GND	16	VCC
6	GND	17	B4
9	A4	16	B5
10	A5	15	B6
11	A6	14	B7
12	A7	13	$\overline{GBA}$

7411620 (PLCC)

Pin	Signal	Pin	Signal
4	B2	5	B1
3	B3	6	B0
2	VCC	7	GAB
1	NC	8	NC
28	VCC	9	A0
27	B4	10	A1
26	B5	11	A2
25	B6	12	A3
24	B7	13	GND
23	$\overline{GBA}$	14	GND
22	NC	15	NC
21	A7	16	GND
20	A6	17	GND
19	A5	16	A4

7411623

Pin	Signal	Pin	Signal
1	A0	24	GAB
2	A1	23	B0
3	A2	22	B1
4	A3	21	B2
5	GND	20	B3
6	GND	19	VCC
7	GND	18	VCC
6	GND	17	B4
9	A4	16	B5
10	A5	15	B6
11	A6	14	B7
12	A7	13	$\overline{GBA}$

7411623 (PLCC)

Pin	Signal	Pin	Signal
4	B2	5	B1
3	B3	6	B0
2	VCC	7	GAB
1	NC	8	NC
28	VCC	9	A0
27	B4	10	A1
26	B5	11	A2
25	B6	12	A3
24	B7	13	GND
23	$\overline{GBA}$	14	GND
22	NC	15	NC
21	A7	16	GND
20	A6	17	GND
19	A5	18	A4

7411640

Pin	Signal	Pin	Signal
1	A0	24	DIR
2	A1	23	B0
3	A2	22	B1
4	A3	21	B2
5	GND	20	B3
6	GND	19	VCC
7	GND	16	VCC
6	GND	17	B4
9	A4	16	B5
10	A5	15	B6
11	A6	14	B7
12	A7	13	$\overline{EN}$

7411640 (PLCC)

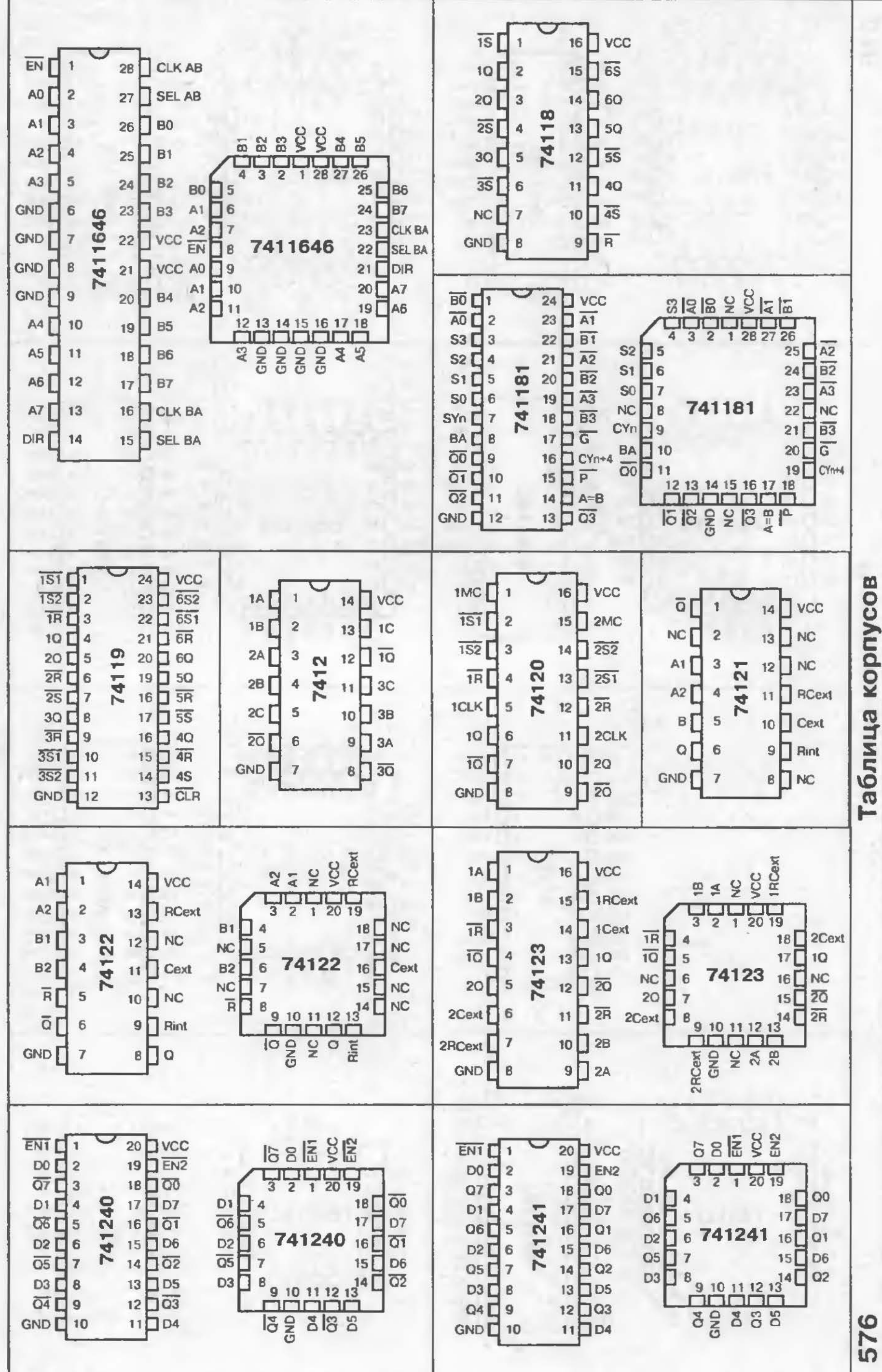
Pin	Signal	Pin	Signal
4	B2	5	B1
3	B3	6	B0
2	VCC	7	DIR
1	NC	6	NC
28	VCC	9	A0
27	B4	10	A1
26	B5	11	A2
25	B6	12	A3
24	B7	13	GND
23	$\overline{EN}$	14	GND
22	NC	15	NC
21	A7	16	GND
20	A6	17	GND
19	A5	16	A4

7411643

Pin	Signal	Pin	Signal
1	A0	24	DIR
2	A1	23	B0
3	A2	22	B1
4	A3	21	B2
5	GND	20	B3
6	GND	19	VCC
7	GND	18	VCC
8	GND	17	B4
9	A4	16	B5
10	A5	15	B8
11	A6	14	B7
12	A7	13	$\overline{EN}$

7411643 (PLCC)

Pin	Signal	Pin	Signal
4	B2	5	B1
3	B3	6	B0
2	VCC	7	DIR
1	NC	8	NC
28	VCC	9	A0
27	B4	10	A1
26	B5	11	A2
25	B6	12	A3
24	B7	13	GND
23	$\overline{EN}$	14	GND
22	NC	15	NC
21	A7	16	GND
20	A6	17	GND
19	A5	18	A4


7411646
EN 1 28 CLK AB
A0 2 27 SEL AB
A1 3 26 B0
A2 4 25 B1
A3 5 24 B2
GND 6 23 B3
GND 7 22 VCC
GND 8 21 VCC
GND 9 20 B4
A4 10 19 B5
A5 11 18 B6
A6 12 17 B7
A7 13 16 CLK BA
DIR 14 15 SEL BA
7411646
B1 B2 B3 VCC VCC B4 B5
4 3 2 1 28 27 26
B0 5 25 B6
A1 6 24 B7
A2 7 23 CLK BA
EN 8 22 SEL BA
A0 9 21 DIR
A1 10 20 A7
A2 11 19 A6
12 13 14 15 16 17 18
A3 GND GND GND GND A4 A5
74118
1S 1 16 VCC
1Q 2 15 6S
2Q 3 14 6Q
2S 4 13 5Q
3Q 5 12 5S
3S 6 11 4Q
NC 7 10 4S
GND 8 9 R
741181
B0 1 24 VCC
A0 2 23 A1
S3 3 22 B1
S2 4 21 A2
S1 5 20 B2
S0 6 19 A3
SYn 7 18 B3
BA 8 17 G
Q0 9 16 CYn+4
Q1 10 15 P
Q2 11 14 A=B
GND 12 13 Q3
741181
S3 A0 B0 NC VCC A1 B1
4 3 2 1 28 27 26
S2 5 25 A2
S1 6 24 B2
S0 7 23 A3
NC 8 22 NC
CYn 9 21 B3
BA 10 20 G
Q0 11 19 CYn+4
12 13 14 15 16 17 18
Q1 Q2 GND NC Q3 A=B P
74119
1S1 1 24 VCC
1S2 2 23 6S2
1R 3 22 6S1
1Q 4 21 6R
2Q 5 20 6Q
2R 6 19 5Q
2S 7 18 5R
3Q 8 17 5S
3R 9 16 4Q
3S1 10 15 4R
3S2 11 14 4S
GND 12 13 CLR
7412
1A 1 14 VCC
1B 2 13 1C
2A 3 12 1Q
2B 4 11 3C
2C 5 10 3B
2Q 6 9 3A
GND 7 8 3Q
74120
1MC 1 16 VCC
1S1 2 15 2MC
1S2 3 14 2S2
1R 4 13 2S1
1CLK 5 12 2R
1Q 6 11 2CLK
1Q 7 10 2Q
GND 8 9 2Q
74121
Q 1 14 VCC
NC 2 13 NC
A1 3 12 NC
A2 4 11 RCext
B 5 10 Cext
Q 6 9 Rint
GND 7 8 NC
74122
A1 1 14 VCC
A2 2 13 RCext
B1 3 12 NC
B2 4 11 Cext
R 5 10 NC
Q 6 9 Rint
GND 7 8 Q
74122
A2 A1 NC VCC RCext
3 2 1 20 19
B1 4 18 NC
NC 5 17 NC
B2 6 16 Cext
NC 7 15 NC
R 8 14 NC
9 10 11 12 13
Q GND NC Q Rint
74123
1A 1 16 VCC
1B 2 15 1RCext
1R 3 14 1Cext
1Q 4 13 1Q
2Q 5 12 2Q
2Cext 6 11 2R
2RCext 7 10 2B
GND 8 9 2A
74123
1B 1A NC VCC 1RCext
3 2 1 20 19
1R 4 18 2Cext
1Q 5 17 1Q
NC 6 16 NC
2Q 7 15 2Q
2Cext 8 14 2R
9 10 11 12 13
2RCext GND NC 2A 2B
741240
EN1 1 20 VCC
D0 2 19 EN2
Q7 3 18 Q0
D1 4 17 D7
Q6 5 16 Q1
D2 6 15 D6
Q5 7 14 Q2
D3 8 13 D5
Q4 9 12 Q3
GND 10 11 D4
741240
Q7 D0 EN1 VCC EN2
3 2 1 20 19
D1 4 18 Q0
Q6 5 17 D7
D2 6 16 Q1
Q5 7 15 D6
D3 8 14 Q2
9 10 11 12 13
Q4 GND D4 Q3 D5
741241
EN1 1 20 VCC
D0 2 19 EN2
Q7 3 18 Q0
D1 4 17 D7
Q6 5 16 Q1
D2 6 15 D6
Q5 7 14 Q2
D3 8 13 D5
Q4 9 12 Q3
GND 10 11 D4
741241
Q7 D0 EN1 VCC EN2
3 2 1 20 19
D1 4 18 Q0
Q6 5 17 D7
D2 6 16 Q1
Q5 7 15 D6
D3 8 14 Q2
9 10 11 12 13
Q4 GND D4 Q3 D5

74124/1

Pin	Signal	Pin	Signal
1	2FC	16	VCC
2	1FC	15	VCC OSC
3	1Ber	14	2Ber
4	1Cext	13	2Cext
5	1Cext	12	2Cext
6	$\overline{1EN}$	11	$\overline{2EN}$
7	$\overline{1Q}$	10	$\overline{2Q}$
6	GND OSC	9	GND

74124/1 (PLCC)

Pin	Signal	Pin	Signal
3	1FC	4	1Ber
2	2FC	5	1Cext
1	NC	6	NC
20	VCC	7	1Cext
19	VCC OSC	8	$\overline{1EN}$
18	2Ber	9	$\overline{1Q}$
17	2Cext	10	GND OSC
16	NC	11	NC
15	2Cext	12	GND
14	$\overline{2EN}$	13	$\overline{2Q}$

741242

Pin	Signal	Pin	Signal
1	$\overline{GAB}$	14	VCC
2	NC	13	GBA
3	A0	12	NC
4	A1	11	B0
5	A2	10	B1
6	A3	9	B2
7	GND	8	B3

741242 (PLCC)

Pin	Signal	Pin	Signal
3	NC	4	A0
2	$\overline{GAB}$	5	NC
1	NC	6	A1
20	VCC	7	NC
19	GBA	8	A2
18	NC	9	A3
17	NC	10	GND
16	B0	11	NC
15	NC	12	B3
14	B1	13	B2

74124/2

Pin	Signal	Pin	Signal
1	1Cext	14	VCC
2	1RCext	13	2Rin1
3	1Rint	12	2RCext
4	$\overline{1TR-}$	11	2Cext
5	1TR+	10	2O
6	1Q	9	$\overline{2Q}$
7	GND	8	EN

741243

Pin	Signal	Pin	Signal
1	$\overline{GAB}$	14	VCC
2	NC	13	GBA
3	A0	12	NC
4	A1	11	B0
5	A2	10	B1
6	A3	9	B2
7	GND	8	B3

741243 (PLCC)

Pin	Signal	Pin	Signal
3	NC	4	A0
2	$\overline{GAB}$	5	NC
1	NC	6	A1
20	VCC	7	NC
19	GBA	6	A2
16	NC	9	A3
17	NC	10	GND
16	B0	11	NC
15	NC	12	B3
14	B1	13	B2

741244

Pin	Signal	Pin	Signal
1	$\overline{EN1}$	20	VCC
2	D0	19	$\overline{EN2}$
3	O7	18	Q0
4	D1	17	D7
5	Q6	16	O1
6	D2	15	D6
7	O5	14	O2
8	D3	13	D5
9	Q4	12	O3
10	GND	11	D4

741244 (PLCC)

Pin	Signal	Pin	Signal
3	O7	4	D1
2	D0	5	Q6
1	$\overline{EN1}$	6	D2
20	VCC	7	Q5
19	$\overline{EN2}$	8	D3
18	O0	9	Q4
17	D7	10	GND
16	Q1	11	D4
15	D6	12	Q3
14	O2	13	D5

741245 (PLCC)

Pin	Signal	Pin	Signal
3	A1	4	A2
2	A0	5	A3
1	DIR AB/$\overline{BA}$	6	A4
20	VCC	7	A5
19	$\overline{EN}$	8	A6
18	B0	9	A7
17	B1	10	GND
16	B2	11	B7
15	B3	12	B6
14	B4	13	B5

74125

Pin	Signal	Pin	Signal
1	$\overline{1C}$	14	VCC
2	1A	13	$\overline{4C}$
3	1O	12	4A
4	$\overline{2C}$	11	4O
5	2A	10	$\overline{3C}$
6	2O	9	3A
7	GND	8	3Q

74125 (PLCC)

Pin	Signal	Pin	Signal
3	1A	4	1Q
2	$\overline{1C}$	5	NC
1	NC	6	$\overline{2C}$
20	VCC	7	NC
19	$\overline{4C}$	8	2A
18	4A	9	2Q
17	NC	10	GND
16	4O	11	NC
15	NC	12	3Q
14	$\overline{3C}$	13	3A

74126

Pin	Signal	Pin	Signal
1	1C	14	VCC
2	1A	13	4C
3	1Q	12	4A
4	2C	11	4O
5	2A	10	3C
6	2O	9	3A
7	GND	8	3O

74126 (PLCC)

Pin	Signal	Pin	Signal
3	1A	4	1O
2	1C	5	NC
1	NC	6	2C
20	VCC	7	NC
19	4C	8	2A
18	4A	9	2O
17	NC	10	GND
16	4Q	11	NC
15	NC	12	3Q
14	3C	13	3A

74128

Pin	Signal	Pin	Signal
1	$\overline{1O}$	14	VCC
2	1A	13	$\overline{4Q}$
3	1B	12	4A
4	$\overline{2O}$	11	4B
5	2A	10	$\overline{3O}$
6	2B	9	3A
7	GND	8	3B

7413 (PLCC)

Pin	Signal	Pin	Signal
3	1B	4	NC
2	1A	5	NC
1	NC	6	1C
20	VCC	7	NC
19	2D	8	1D
18	2C	9	$\overline{1Q}$
17	NC	10	GND
16	NC	11	NC
15	NC	12	$\overline{2Q}$
14	2B	13	2A

74130

Pin	Signal	Pin	Signal
1	1B	14	VCC
2	1A	13	4B
3	1O	12	4A
4	2B	11	4O
5	2A	10	3B
6	2Q	9	3A
7	GND	8	3O

74131

DIP: 1 A0, 2 A1, 3 A2, 4 CLK, 5 $\overline{EN2}$, 6 EN1, 7 Q7, 8 GND, 9 Q6, 10 Q5, 11 Q4, 12 Q3, 13 Q2, 14 Q1, 15 Q0, 16 VCC

PLCC 74131: 1 NC, 2 A0, 3 A1, 4 A2, 5 CLK, 6 NC, 7 $\overline{EN2}$, 8 EN1, 9 Q7, 10 GND, 11 NC, 12 Q6, 13 Q5, 14 Q4, 15 Q3, 16 NC, 17 Q2, 18 Q1, 19 Q0, 20 VCC

74131/1

DIP: 1 A0, 2 A1, 3 A2, 4 CLK, 5 $\overline{EN2}$, 6 EN1, 7 Q7, 8 GND, 9 Q6, 10 Q5, 11 Q4, 12 Q3, 13 Q2, 14 Q1, 15 Q0, 16 VCC

PLCC 74131/1: 1 NC, 2 A0, 3 A1, 4 A2, 5 CLK, 6 NC, 7 $\overline{EN2}$, 8 EN1, 9 Q7, 10 GND, 11 NC, 12 Q6, 13 Q5, 14 Q4, 15 Q3, 16 NC, 17 Q2, 18 Q1, 19 Q0, 20 VCC

74131/2

DIP: 1 1B, 2 1A, 3 1Q, 4 2B, 5 2A, 6 2Q, 7 GND, 8 3Q, 9 3A, 10 3B, 11 4Q, 12 4A, 13 4B, 14 VCC

74132

DIP: 1 1B, 2 1A, 3 $\overline{1Q}$, 4 2B, 5 2A, 6 $\overline{2Q}$, 7 GND, 8 $\overline{3Q}$, 9 3A, 10 3B, 11 $\overline{4Q}$, 12 4A, 13 4B, 14 VCC

74133

DIP: 1 G, 2 F, 3 E, 4 D, 5 C, 6 B, 7 A, 8 GND, 9 $\overline{Q}$, 10 H, 11 I, 12 J, 13 K, 14 L, 15 M, 16 VCC

PLCC 74133: 3 F, 2 G, 1 NC, 20 VCC, 19 M; 4 E, 5 D, 6 NC, 7 C, 6 B; 18 L, 17 K, 18 NC, 15 J, 14 I; 9 A, 10 GND, 11 NC, 12 $\overline{Q}$, 13 H

74134

DIP: 1 G, 2 F, 3 E, 4 D, 5 C, 6 B, 7 A, 8 GND, 9 $\overline{Q}$, 10 H, 11 I, 12 J, 13 K, 14 L, 15 $\overline{EN}$, 16 VCC

PLCC 74134: 3 F, 2 G, 1 NC, 20 VCC, 19 $\overline{EN}$; 4 E, 5 D, 6 NC, 7 C, 8 B; 18 L, 17 K, 16 NC, 15 J, 14 I; 9 A, 10 GND, 11 NC, 12 $\overline{Q}$, 13 H

74135

DIP: 1 1A, 2 1B, 3 1Q, 4 1C, 2C, 5 2A, 6 2B, 7 2Q, 8 GND, 9 3Q, 10 3A, 11 3B, 12 3C, 4C, 13 4Q, 14 4A, 15 4B, 16 VCC

PLCC 74135: 3 1B, 2 1A, 1 NC, 20 VCC, 19 4B; 4 1Q, 5 1C, 2C, 8 NC, 7 2A, 8 2B; 18 4A, 17 4Q, 18 NC, 15 3C, 4C, 14 3B; 9 2Q, 10 GND, 11 NC, 12 3Q, 13 3A

74136

DIP: 1 1A, 2 1B, 3 1Q, 4 2A, 5 2B, 6 2Q, 7 GND, 8 3Q, 9 3B, 10 3A, 11 4Q, 12 4B, 13 4A, 14 VCC

PLCC 74136: 3 1B, 2 1A, 1 NC, 20 VCC, 19 4A; 4 1Q, 5 NC, 6 2A, 7 NC, 8 2B; 18 4B, 17 NC, 18 4Q, 15 NC, 14 3A; 9 2Q, 10 GND, 11 NC, 12 3Q, 13 3B

74137

DIP: 1 A0, 2 A1, 3 A2, 4 $\overline{ENL}$, 5 $\overline{EN2}$, 6 EN1, 7 $\overline{Q7}$, 8 GND, 9 $\overline{Q6}$, 10 $\overline{Q5}$, 11 $\overline{Q4}$, 12 $\overline{Q3}$, 13 $\overline{Q2}$, 14 $\overline{Q1}$, 15 $\overline{Q0}$, 16 VCC

PLCC 74137: 3 A1, 2 A0, 1 NC, 20 VCC, 19 $\overline{Q0}$; 4 A2, 5 $\overline{ENL}$, 8 NC, 7 $\overline{EN2}$, 8 EN1; 18 $\overline{Q1}$, 17 $\overline{Q2}$, 16 NC, 15 $\overline{Q3}$, 14 $\overline{Q4}$; 9 $\overline{Q7}$, 10 GND, 11 NC, 12 $\overline{Q6}$, 13 $\overline{Q5}$

74138

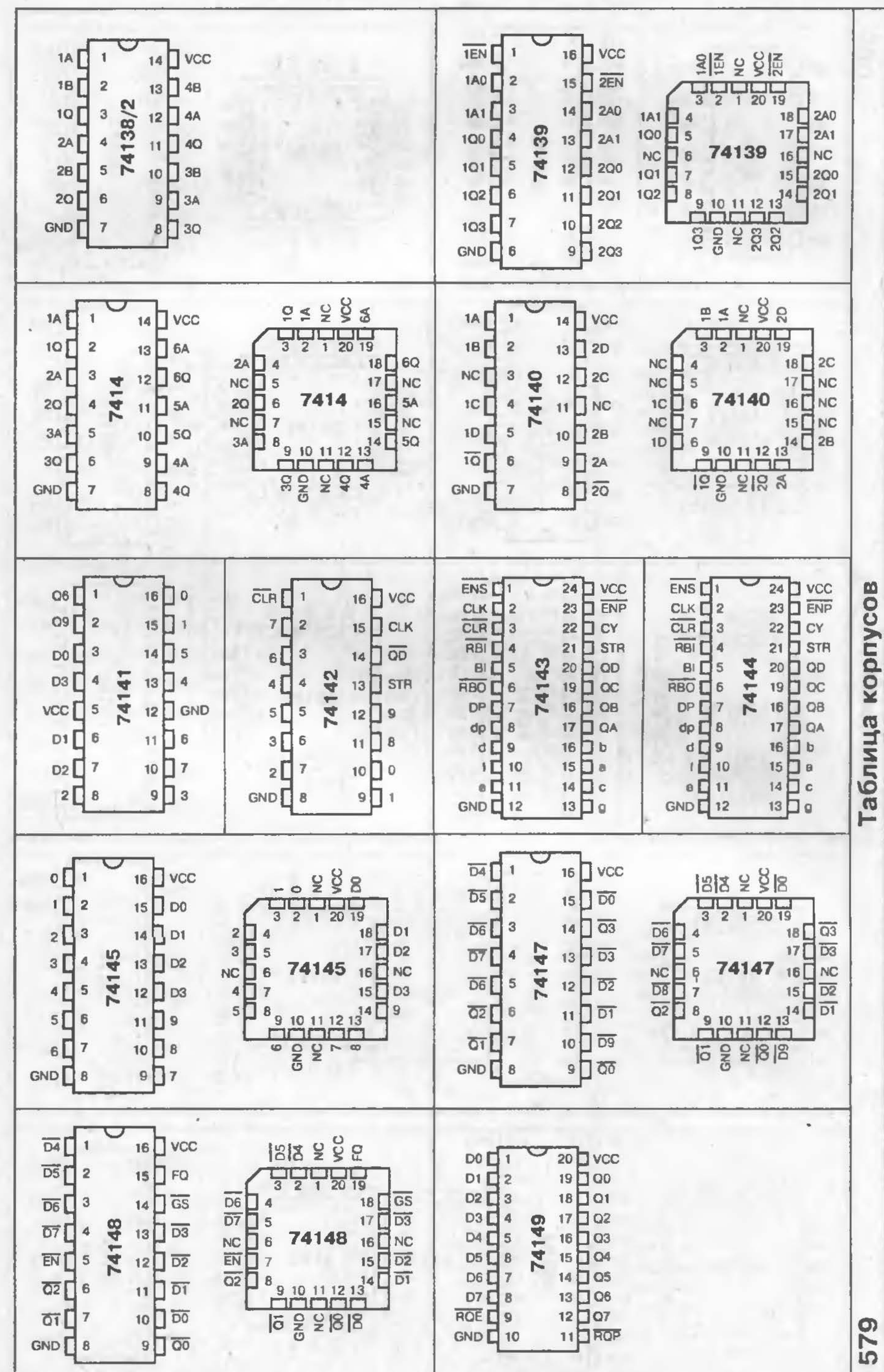
DIP: 1 A0, 2 A1, 3 A2, 4 $\overline{EN2}$, 5 $\overline{EN3}$, 8 EN1, 7 $\overline{Q7}$, 8 GND, 9 $\overline{Q6}$, 10 $\overline{Q5}$, 11 $\overline{Q4}$, 12 $\overline{Q3}$, 13 $\overline{Q2}$, 14 $\overline{Q1}$, 15 $\overline{Q0}$, 16 VCC

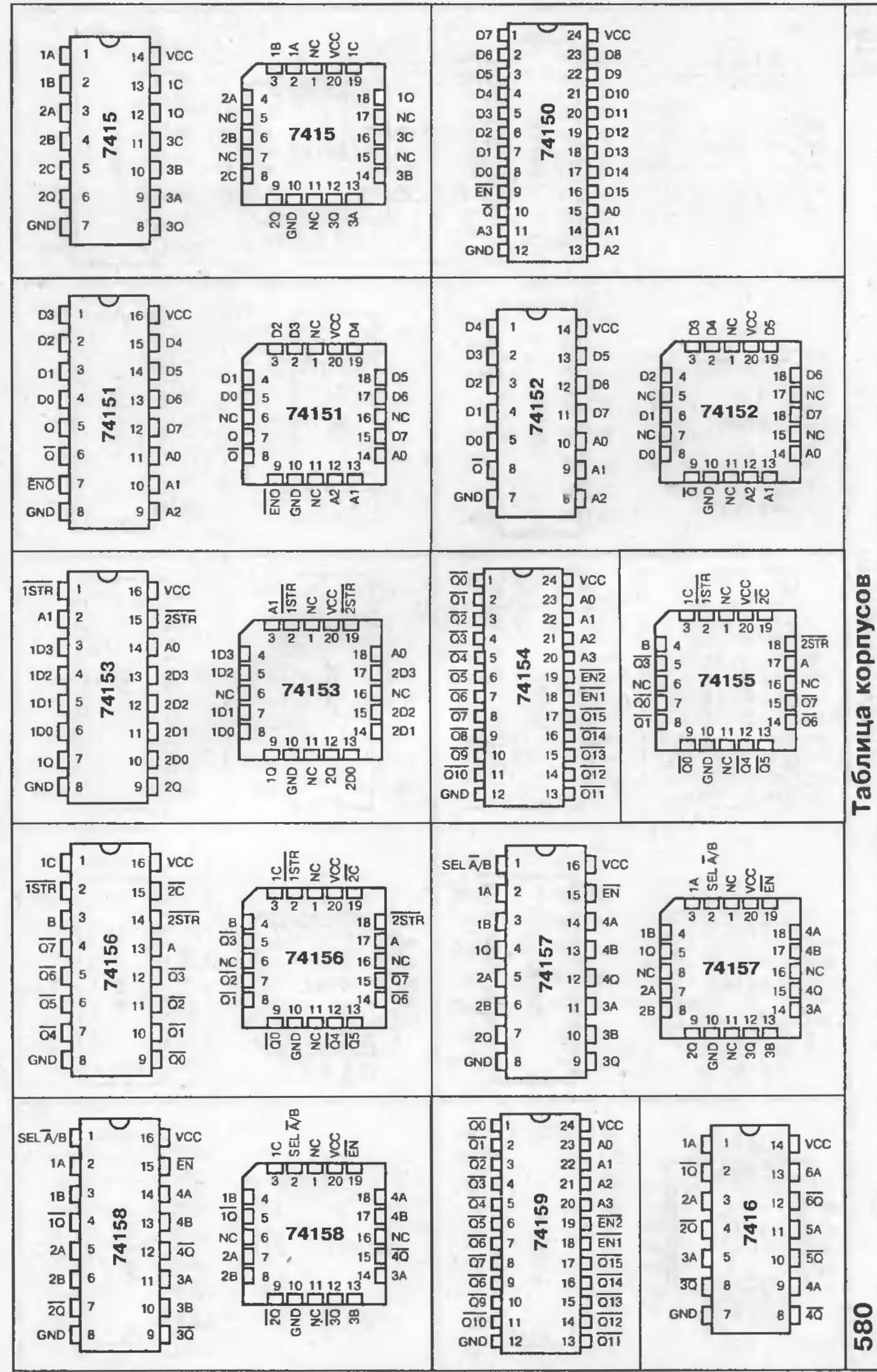
PLCC 74138: 3 A1, 2 A0, 1 NC, 20 VCC, 19 $\overline{Q0}$; 4 A2, 5 $\overline{EN2}$, 6 NC, 7 $\overline{EN3}$, 8 EN1; 18 $\overline{Q1}$, 17 $\overline{Q2}$, 16 NC, 15 $\overline{Q3}$, 14 $\overline{Q4}$; 9 $\overline{Q7}$, 10 GND, 11 NC, 12 $\overline{Q6}$, 13 $\overline{Q5}$

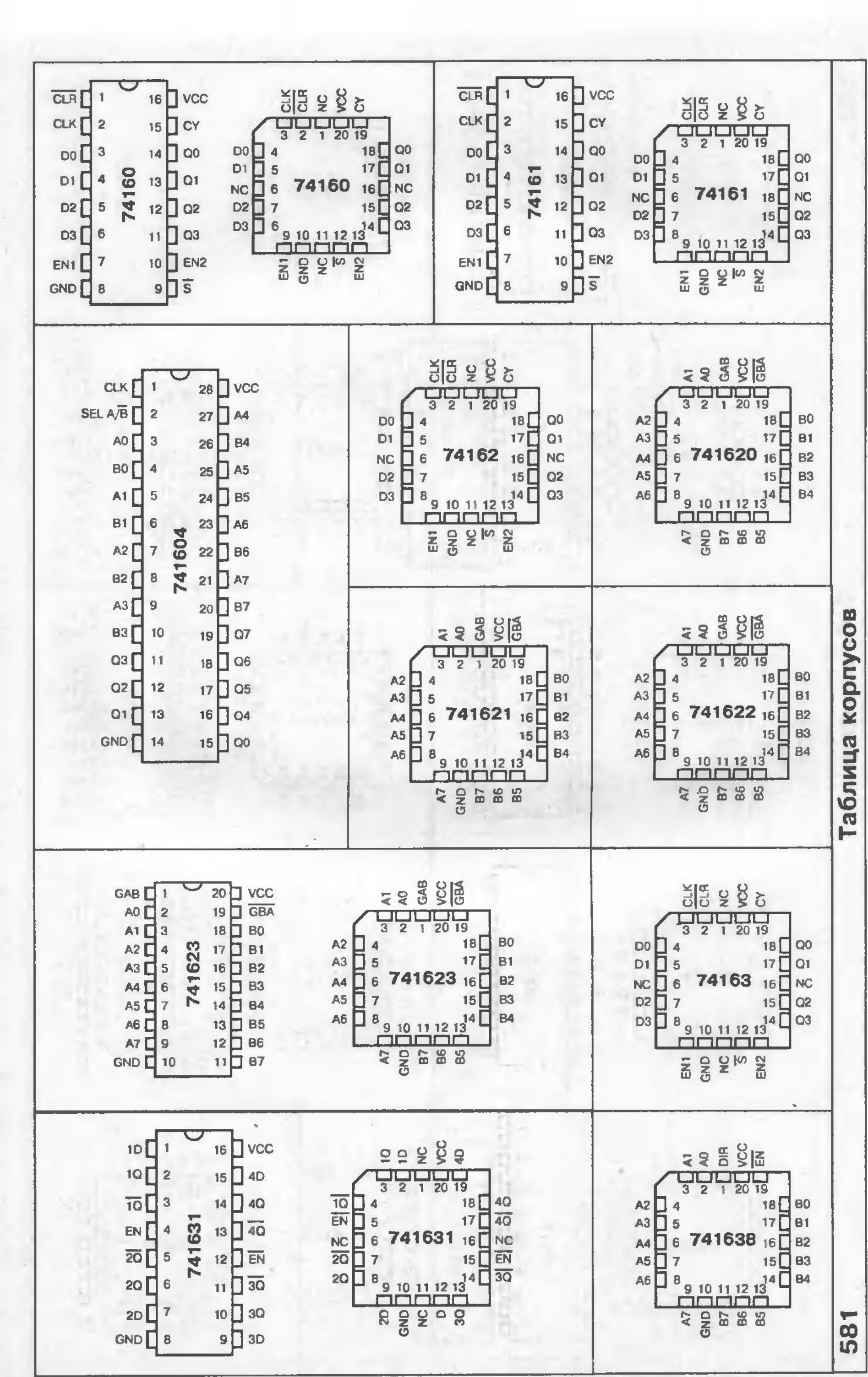
74138/1

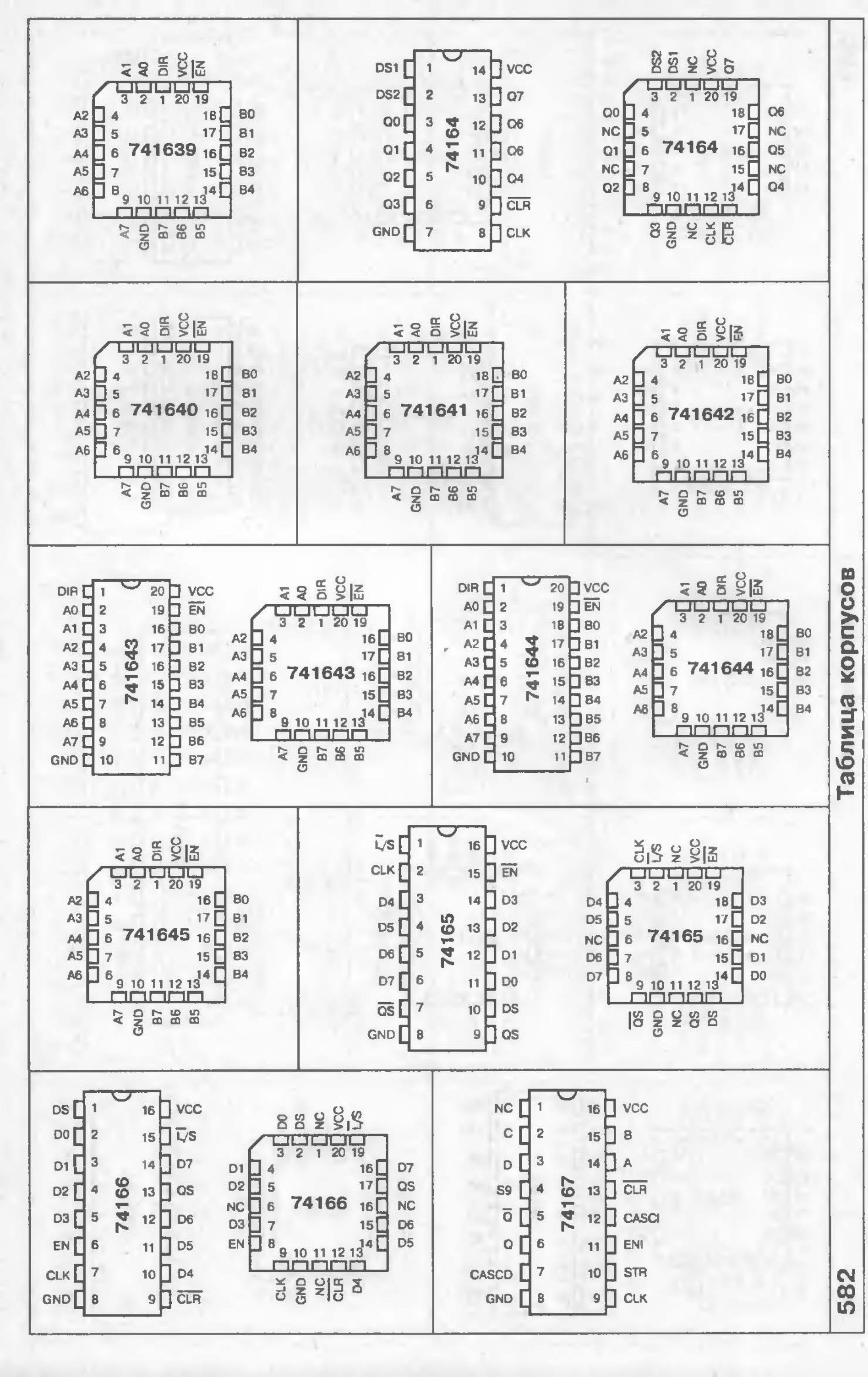
DIP: 1 A, 2 B, 3 C, 4 $\overline{EN2}$, 5 $\overline{EN3}$, 6 EN1, 7 Q7, 8 GND, 9 Q8, 10 Q5, 11 Q4, 12 Q3, 13 Q2, 14 Q1, 15 Q0, 16 VCC

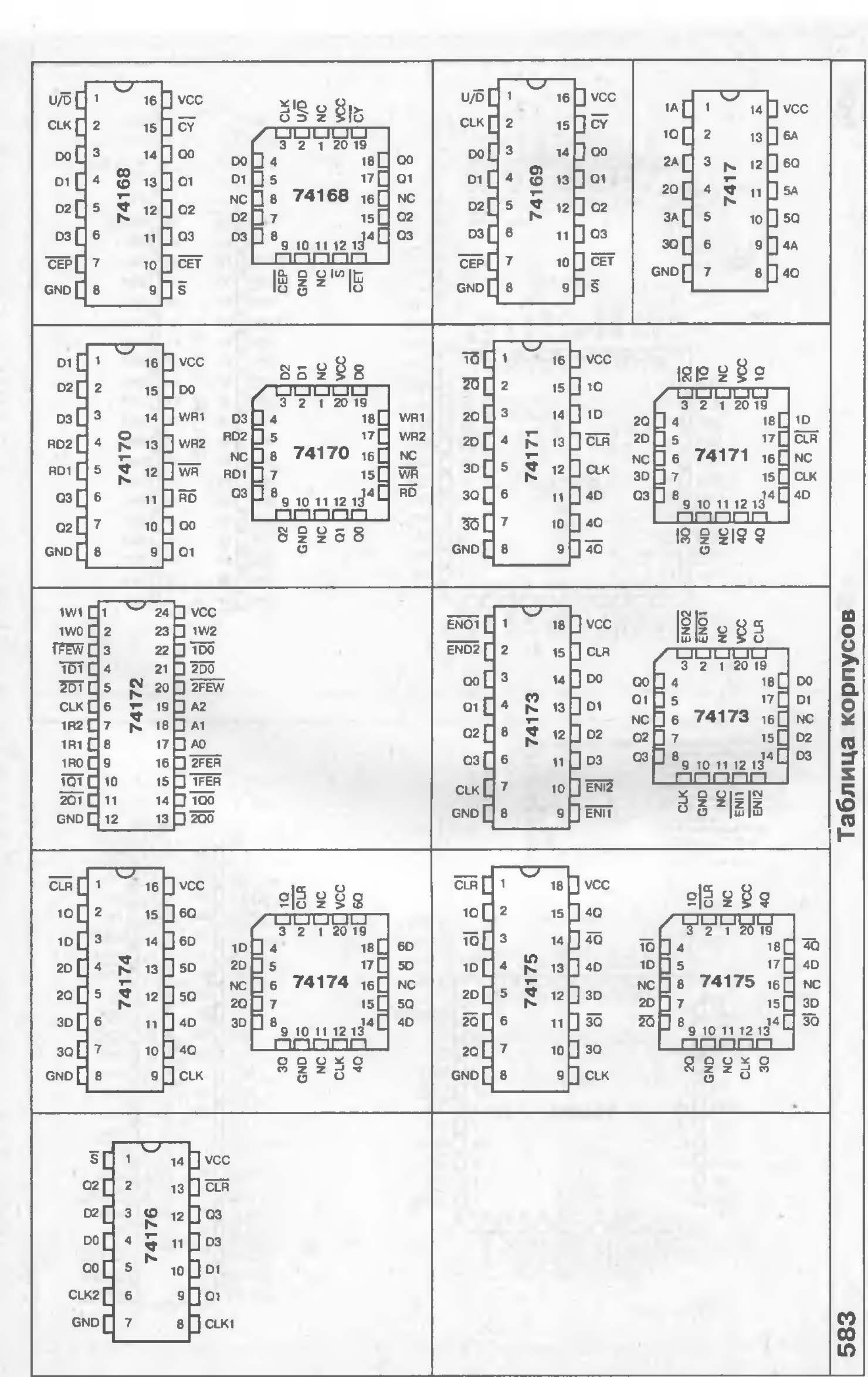
PLCC 74138/1: 3 B, 2 A, 1 NC, 20 VCC, 19 Q0; 4 C, 5 $\overline{EN2}$, 8 NC, 7 $\overline{EN3}$, 8 EN1; 18 Q1, 17 Q2, 16 NC, 15 Q3, 14 Q4; 9 Q7, 10 GND, 11 NC, 12 Q6, 13 Q5

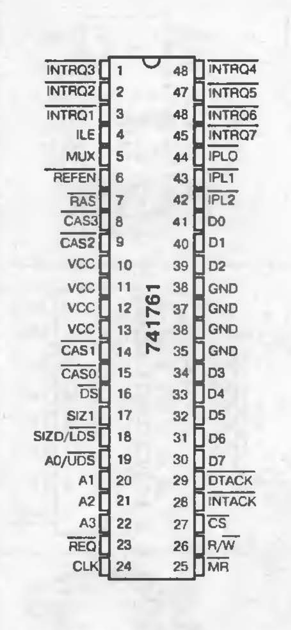

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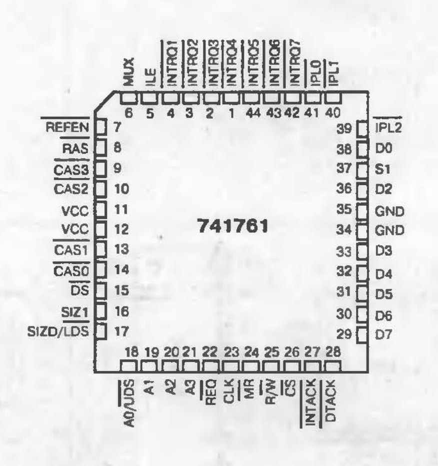

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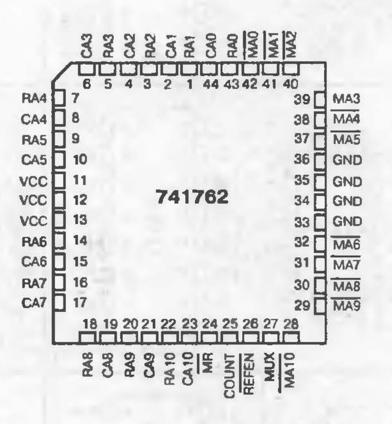

74168
U/D 1 16 VCC
CLK 2 15 CY
D0 3 14 Q0
D1 4 13 Q1
D2 5 12 Q2
D3 6 11 Q3
CEP 7 10 CET
GND 8 9 S
74168
CLK U/D NC VCC CY
3 2 1 20 19
D0 4 18 Q0
D1 5 17 Q1
NC 8 16 NC
D2 7 15 Q2
D3 8 14 Q3
9 10 11 12 13
CEP GND NC S CET
74169
U/D 1 16 VCC
CLK 2 15 CY
D0 3 14 Q0
D1 4 13 Q1
D2 5 12 Q2
D3 6 11 Q3
CEP 7 10 CET
GND 8 9 S
7417
1A 1 14 VCC
1Q 2 13 6A
2A 3 12 6Q
2Q 4 11 5A
3A 5 10 5Q
3Q 6 9 4A
GND 7 8 4Q
74170
D1 1 16 VCC
D2 2 15 D0
D3 3 14 WR1
RD2 4 13 WR2
RD1 5 12 WR
Q3 6 11 RD
Q2 7 10 Q0
GND 8 9 Q1
74170
D2 D1 NC VCC D0
3 2 1 20 19
D3 4 18 WR1
RD2 5 17 WR2
NC 8 16 NC
RD1 7 15 WR
Q3 8 14 RD
9 10 11 12 13
Q2 GND NC Q1 Q0
74171
1Q 1 16 VCC
2Q 2 15 1Q
2Q 3 14 1D
2D 4 13 CLR
3D 5 12 CLK
3Q 6 11 4D
3Q 7 10 4Q
GND 8 9 4Q
74171
2Q 1Q NC VCC 1Q
3 2 1 20 19
2Q 4 18 1D
2D 5 17 CLR
NC 6 16 NC
3D 7 15 CLK
Q3 8 14 4D
9 10 11 12 13
3Q GND NC 4Q 4Q
74172
1W1 1 24 VCC
1W0 2 23 1W2
1FEW 3 22 1D0
1D1 4 21 2D0
2D1 5 20 2FEW
CLK 6 19 A2
1R2 7 18 A1
1R1 8 17 A0
1R0 9 16 2FER
1Q1 10 15 1FER
2Q1 11 14 1Q0
GND 12 13 2Q0
74173
ENO1 1 18 VCC
END2 2 15 CLR
Q0 3 14 D0
Q1 4 13 D1
Q2 8 12 D2
Q3 6 11 D3
CLK 7 10 ENI2
GND 8 9 ENI1
74173
ENO2 ENO1 NC VCC CLR
3 2 1 20 19
Q0 4 18 D0
Q1 5 17 D1
NC 6 16 NC
Q2 7 15 D2
Q3 8 14 D3
9 10 11 12 13
CLK GND NC ENI1 ENI2
74174
CLR 1 16 VCC
1Q 2 15 6Q
1D 3 14 6D
2D 4 13 5D
2Q 5 12 5Q
3D 6 11 4D
3Q 7 10 4Q
GND 8 9 CLK
74174
1Q CLR NC VCC 6Q
3 2 1 20 19
1D 4 18 6D
2D 5 17 5D
NC 6 16 NC
2Q 7 15 5Q
3D 8 14 4D
9 10 11 12 13
3Q GND NC CLK 4Q
74175
CLR 1 18 VCC
1Q 2 15 4Q
1Q 3 14 4Q
1D 4 13 4D
2D 5 12 3D
2Q 6 11 3Q
2Q 7 10 3Q
GND 8 9 CLK
74175
1Q CLR NC VCC 4Q
3 2 1 20 19
1Q 4 18 4Q
1D 5 17 4D
NC 8 16 NC
2D 7 15 3D
2Q 8 14 3Q
9 10 11 12 13
2Q GND NC CLK 3Q
74176
S 1 14 VCC
Q2 2 13 CLR
D2 3 12 Q3
D0 4 11 D3
Q0 5 10 D1
CLK2 6 9 Q1
GND 7 8 CLK1



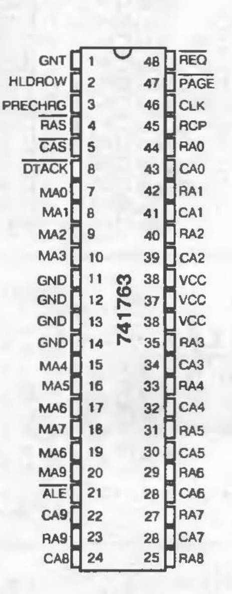


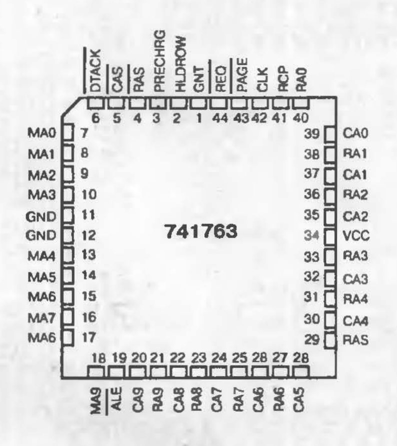
Connections:
REQ DRAM reguest input
SIZO/LDS, SIZI, A0/UDS, A1 byte select inputs
A2, A3 register select inputs
CS, DS chip select, data strobe
R/W read/wnte input
INTACK interrupt acknowledge inputs
ILE interrupt latch enable input
INTRQ interrupt request input
DTACK data transfer acknowledge output
D0 - D7 data bus outputs
IPL interrupt priority outputs
RAS, MUX,CAS, REFEN DRAM control outputs





Connections:
RA0-RA10 row address inputs
CA0-CA10 column address inputs
MA0-MA10 memory address outputs
REFEN refresh enable input
MUX row/clumn address multiplex inp
COUNT refresh counter clock input



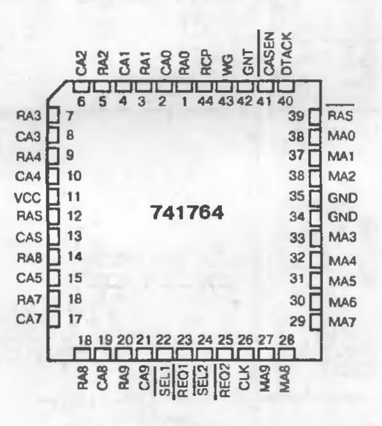


Connections:

REQ	DRAM raguest inoput
PAGE	page mode select input
PRECHRG	RAS precharge select input
HLDROW	row hold select input
DTACK	data transfer ack. output
GNT	access grant output
RCP	refresh clock input
RA0-RA9	row address input
CA0-CA9	column address input
ALE	address latch enable input
RAS	row address strobe output
CAS	column address strobe output
MA0-MA9	DRAM address outputs

741764

NC	1	48	RCP
RA0	2	47	WG
CA0	3	46	GNT
RA1	4	45	CASEN
CA1	5	44	DTACK
RA2	6	43	RAS
CA2	7	42	MA0
RA3	8	41	MA1
CA3	9	40	MA2
RA4	10	39	GND
CA4	11	38	GND
VCC	12	37	GND
VCC	13	38	MA3
VCC	14	35	MA4
RA5	15	34	MA5
CA5	16	33	MA6
RA6	17	32	MA7
CA5	18	31	MA8
RA7	19	30	MA9
CA7	20	29	CLK
RAS	21	28	SEL2
CAS	22	27	REQ2
RA9	23	26	REQ1
CA9	24	25	SEL1



Connections:

REQ	memory access reqest from microprocess
RA0-RA9	row address inputs
CA0-CA9	column address input
MA0-MA9	memory address outputs
GNT	grant output
RAS	row address strobe
WG	write gate
CASEN	column address strobe enable
DTACK	data transfer acknowledge
SEL	select microprocessor
RCP	refresh clock

741765 (DIP-48)

Pin	Signal	Pin	Signal
1	NC	48	RCP
2	RA0	47	WG
3	CA0	46	GNT
4	RA1	45	CASEN
5	CA1	44	DTACK
6	RA2	43	RAS
7	CA2	42	MA0
6	RA3	41	MA1
9	CA3	40	MA2
10	RA4	39	GND
11	CA4	38	GND
12	VCC	37	GND
13	VCC	36	MA3
14	VCC	35	MA4
15	RA5	34	MA5
16	CA5	33	MA6
17	RA6	32	MA7
18	CA6	31	MA6
19	RA7	30	MA9
20	CA7	29	CLK
21	RA6	26	SEL2
22	CA8	27	REQ2
23	RA9	26	REQ1
24	CA9	25	SEL1

741765 (PLCC-44)

Side	Pins
Top	CA2 6, RA2 5, CA1 4, RA1 3, CA0 2, RA0 1, RCP 44, WG 43, GNT 42, CASEN 41, DTACK 40
Left	RA3 7, CA3 6, RA4 9, CA4 10, VCC 11, RA5 12, CA5 13, RA6 14, CA6 15, RA7 16, CA7 17
Right	39 RAS, 36 MA0, 37 MA1, 36 MA2, 35 GND, 34 GND, 33 MA3, 32 MA4, 31 MA5, 30 MA6, 29 MA7
Bottom	18 RA8, 19 CA8, 20 RA9, 21 CA9, 22 SEL1, 23 REQ1, 24 SEL2, 25 REQ2, 26 CLK, 27 MA9, 28 MA8

Connections:

REQ	memory access regest from microproces
RA0-RA9	row address inputs
CA0-CA9	column address input
MA0-MA9	memory address outputs
GNT	grant output
RAS	row address strobe
WG	write gate
CASEN	column address strobe enable
DTACK	data transfer acknowledge
SEL	select mocroprocessor
RCP	refresh clock

74177

Pin	Signal	Pin	Signal
1	S	14	VCC
2	Q2	13	CLR
3	D2	12	Q3
4	D0	11	D3
5	Q0	10	D1
6	CLK2	9	Q1
7	GND	8	CLK1

741779

Pin	Signal	Pin	Signal
1	I/O1	16	I/O0
2	I/O2	15	CLK
3	I/O3	14	CET
4	GND	13	VCC
5	I/O4	12	TC
6	I/O5	11	S0
7	I/O6	10	S1
8	I/O7	9	EN

74178

Pin	Signal	Pin	Signal
1	D1	14	VCC
2	D0	13	D2
3	DS	12	D3
4	Q0	11	EN
5	CLK	10	Q3
6	Q1	9	S
7	GND	6	Q2

74179

Pin	Signal	Pin	Signal
1	CLR	16	VCC
2	D1	15	D2
3	D0	14	D3
4	DS	13	SEL S/L
5	Q0	12	Q3
8	CLK	11	Q3
7	Q1	10	S
8	GND	9	Q2

7418

Pin	Signal	Pin	Signal
1	1A	14	VCC
2	1B	13	2D
3	NC	12	2C
4	1C	11	NC
5	1D	10	2B
6	1Q	9	2A
7	GND	8	2Q

7416

Side	Pins
Top	1B 3, 1A 2, NC 1, VCC 20, 2D 19
Left	NC 4, NC 5, 1C 6, NC 7, 1D 8
Right	18 2C, 17 NC, 16 NC, 15 NC, 14 2B
Bottom	9 1Q, 10 GND, 11 NC, 12 2Q, 13 2A

74180 (DIP)

Pin	Signal	Pin	Signal
1	D6	14	VCC
2	D7	13	D5
3	PE	12	D4
4	PO	11	D3
5	QE	10	D2
6	Q0	9	D1
7	GN0	8	D0

74180 (PLCC)

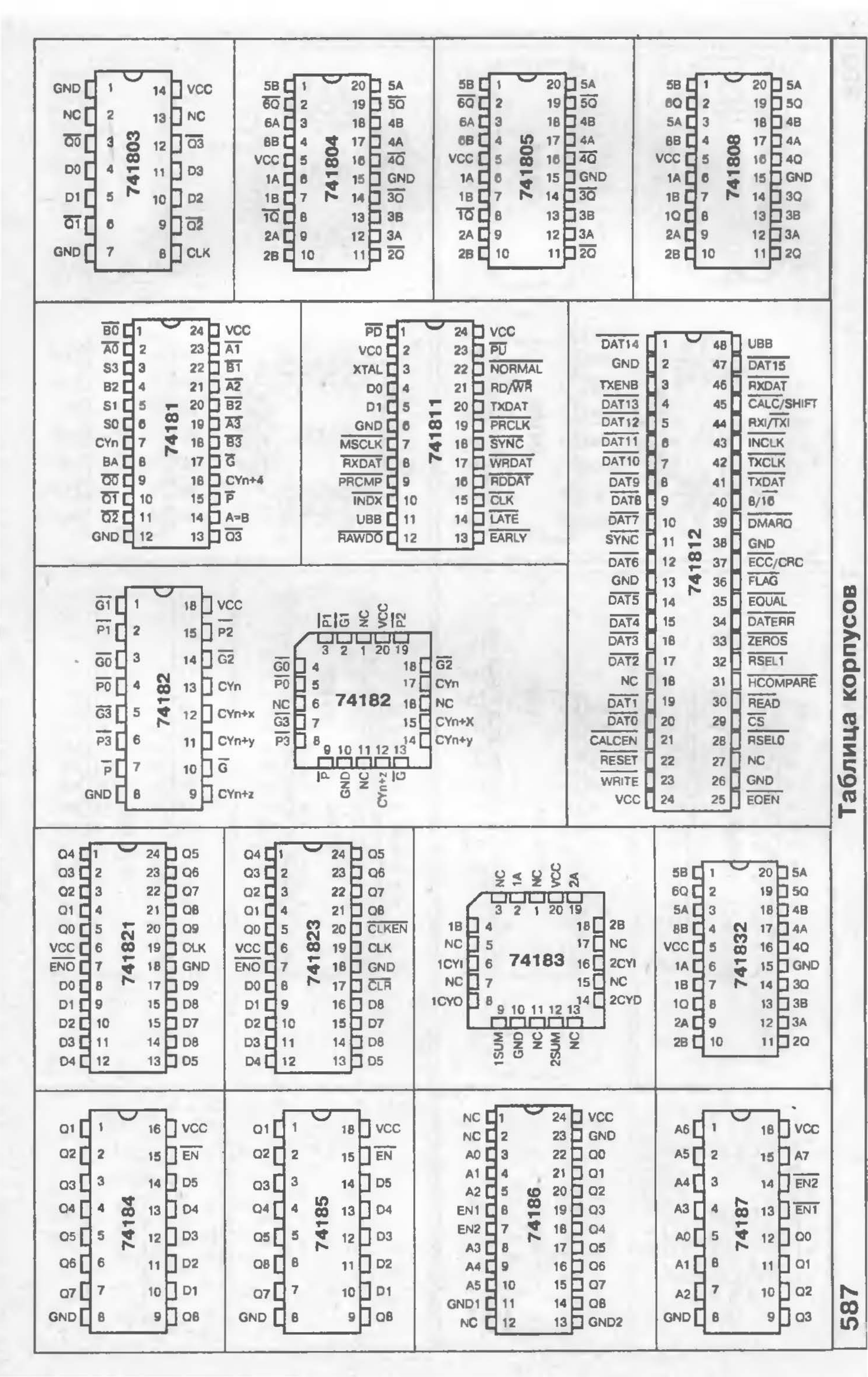
Side	Pins
Top	D7 3, D6 2, NC 1, VCC 20, D5 19
Left	PE 4, NC 5, PO 6, NC 7, QE 6
Right	D4, 17 NC, 16 D3, 15 NC, 14 D2
Bottom	9 QO, 10 GND, 11 NC, 12 D0, 13 D1

741801

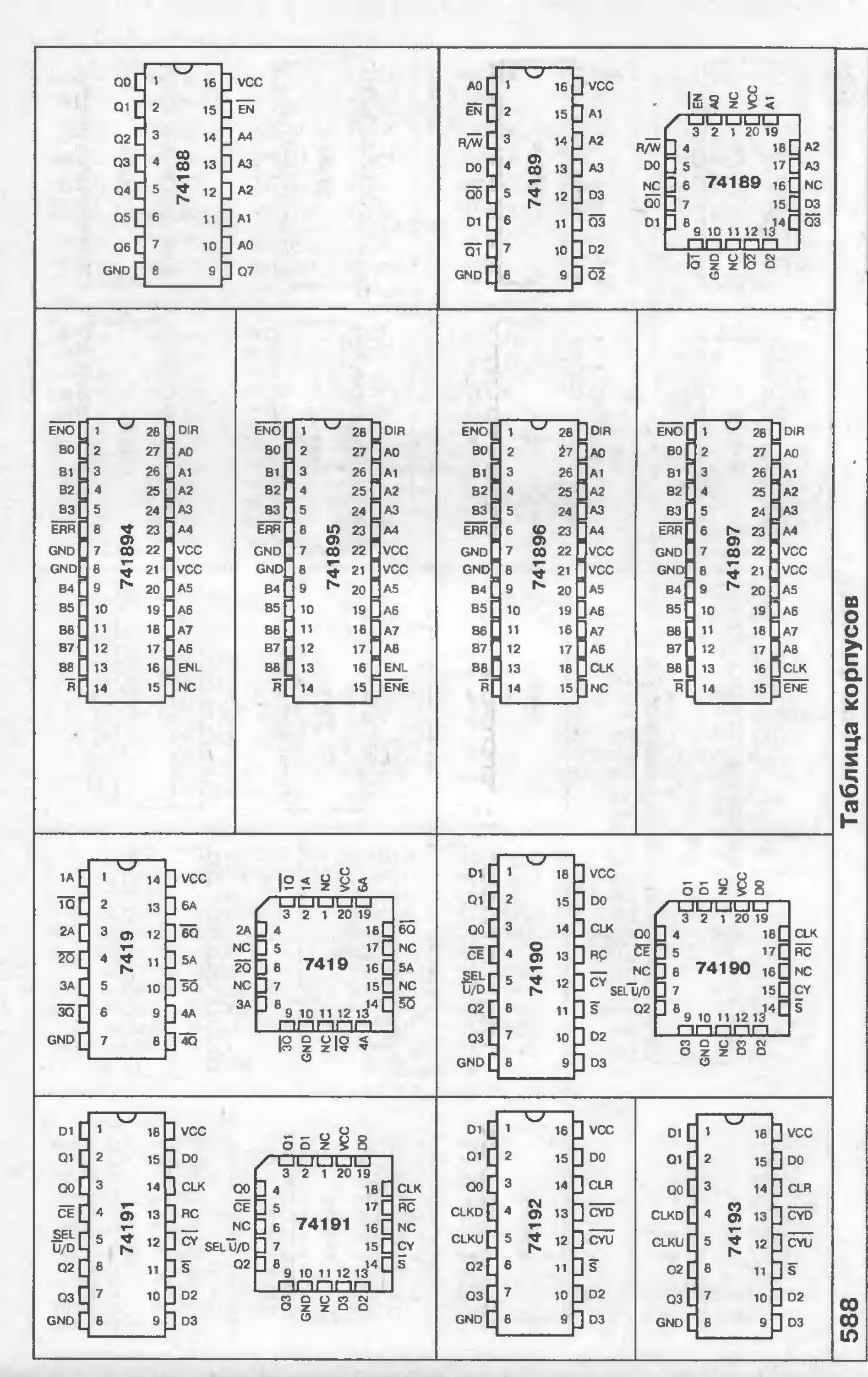
Pin	Signal	Pin	Signal
1	PD	24	VCC
2	VC0	23	PU
3	XTAL	22	NORMAL
4	D0	21	RD/WR
5	D1	20	TXDAT
6	GND	19	PRCLK
7	MSCLK	18	SYNC
8	RXDAT	17	WRDAT
9	PRCMP	16	RDDAT
10	INDX	15	CLK
11	RAWDI	14	LATE
12	RAWDO	13	EARLY

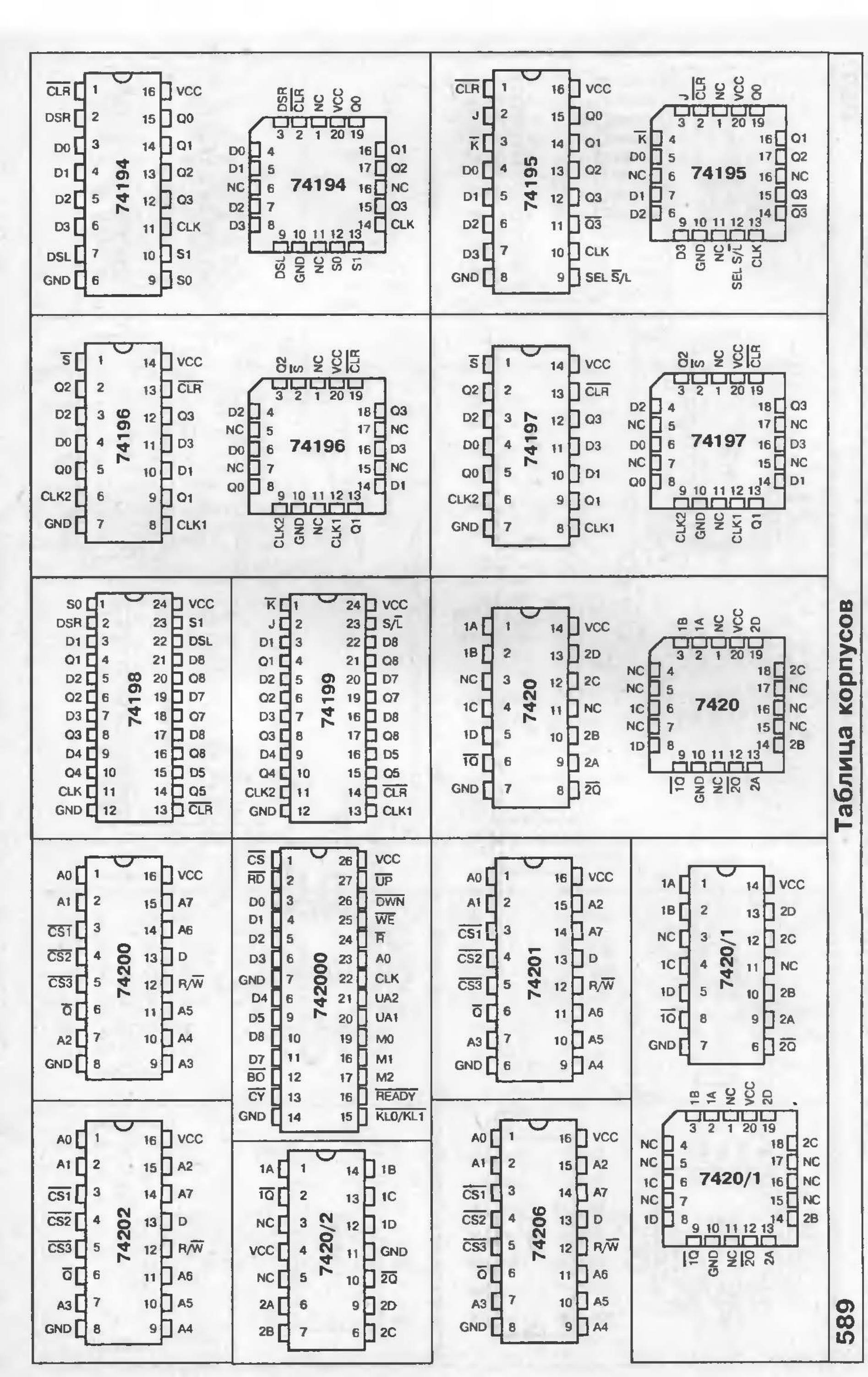
741602

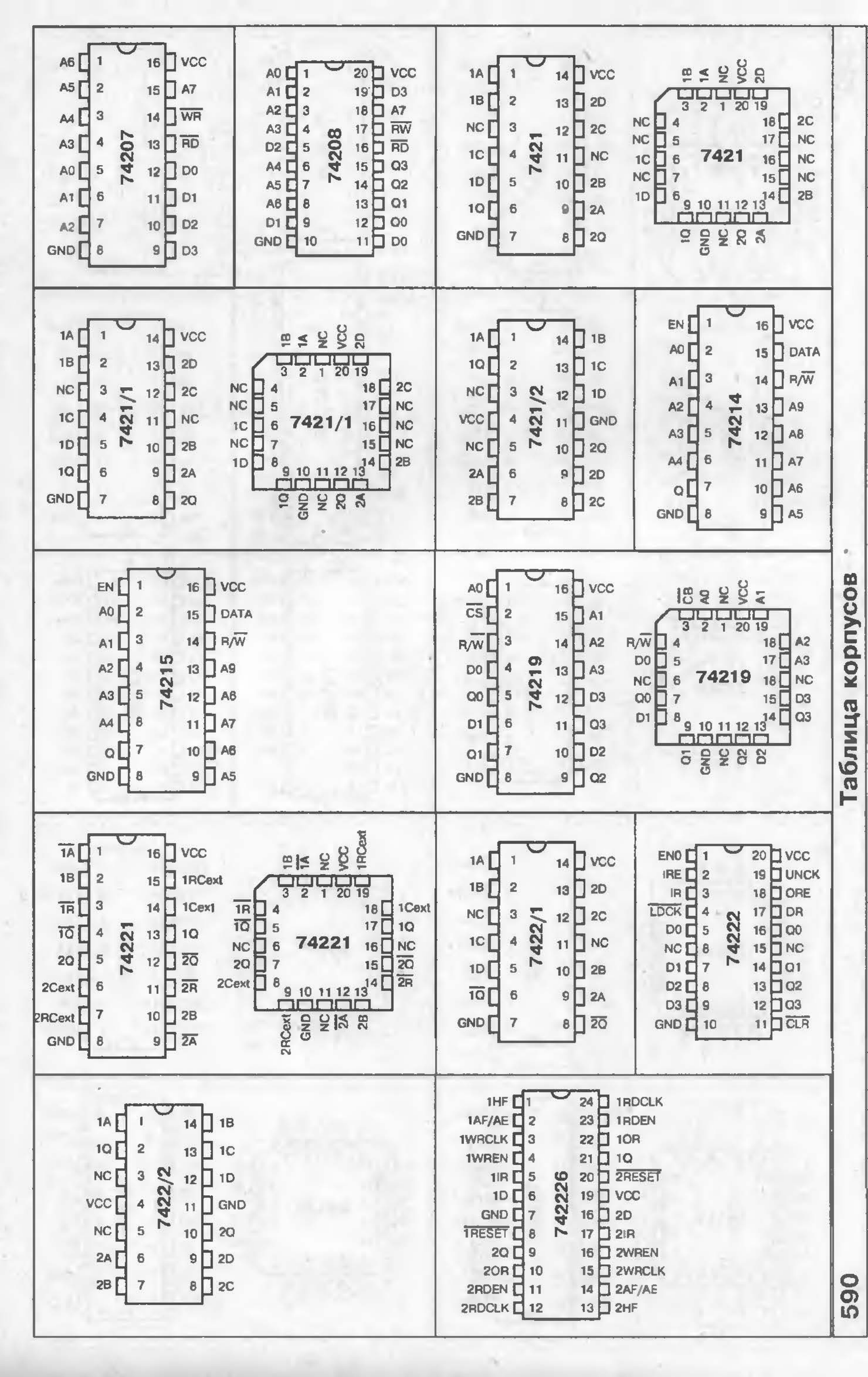
Side	Pins
Top	NC 9, NC 6, DAT11 7, DAT12 6, DAT13 5, NC 4, GND 3, DAT14 2, UBB 1, DAT15 86, NC 67, RXDAT 66, CALK/SHIFT 65, RX1/TX1 64, INCLK 63, NC 62, NC 61
Left	NC 10, NC 11, DAT10 12, DAT9 13, DAT6 14, NC 15, DAT7 16, SYNC 17, DAT6 18, GND 19, NC 20, DAT5 21, DAT4 22, DAT3 23, DAT2 24, NC 25, NC 26
Right	60 NC, 59 NC, 56 TXCLK, 57 TXDAT, 56 8/16, 55 NC, 54 DMARQ, 53 GND, 52 NC, 51 ECC/CRC, 50 FLAG, 49 EQUAL, 48 DATERR, 47 ZEROS, 46 RSEL1, 45 NC, 44 NC
Bottom	27 NC, 28 DAT1, 29 DAT0, 30 CALCEN, 31 NC, 32 RESET, 33 NC, 34 WRITE, 35 VCC, 36 EQEN, 37 GND, 38 NC, 39 RSEL0, 40 C8, 41 READ, 42 NC, 43 NC

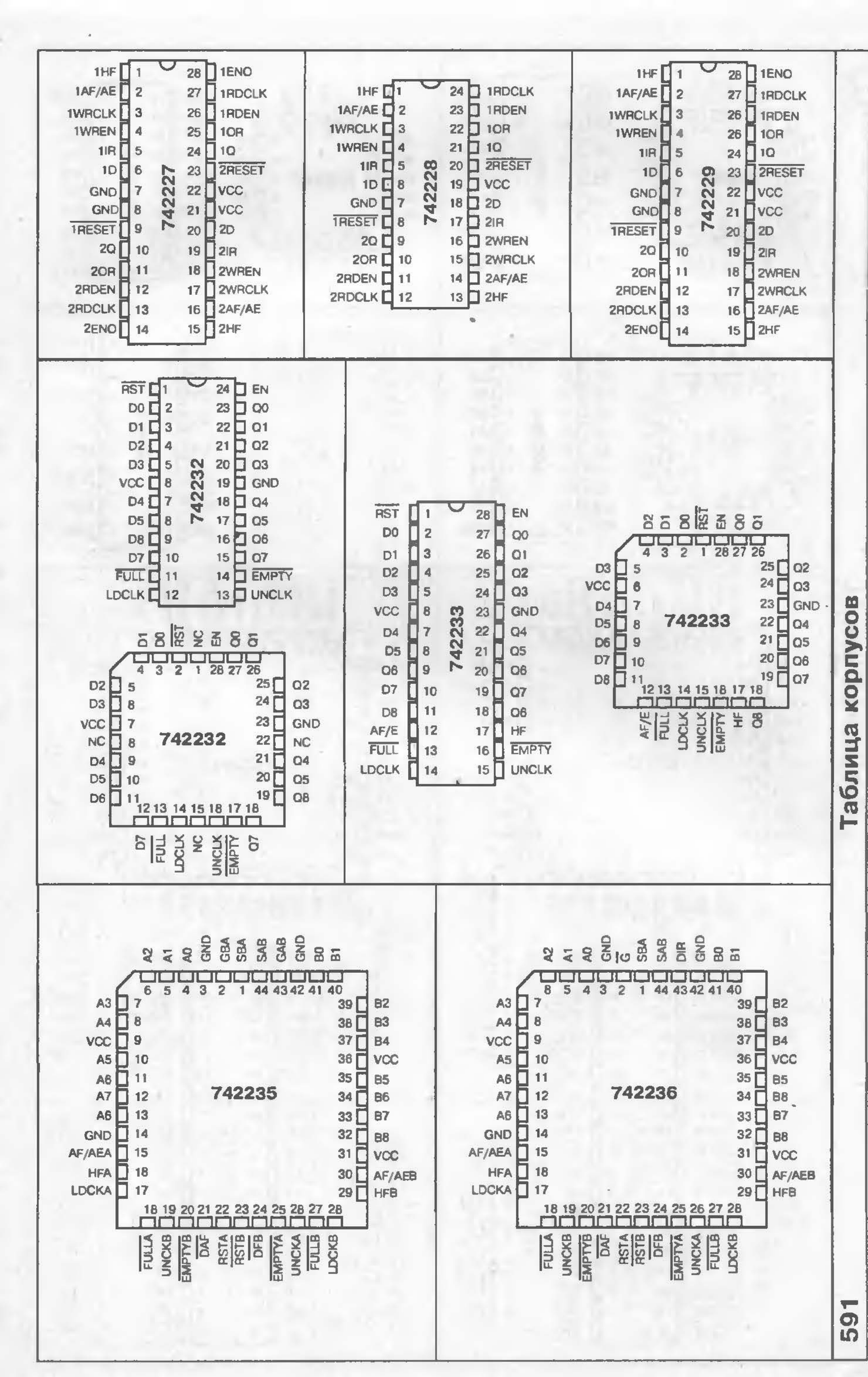


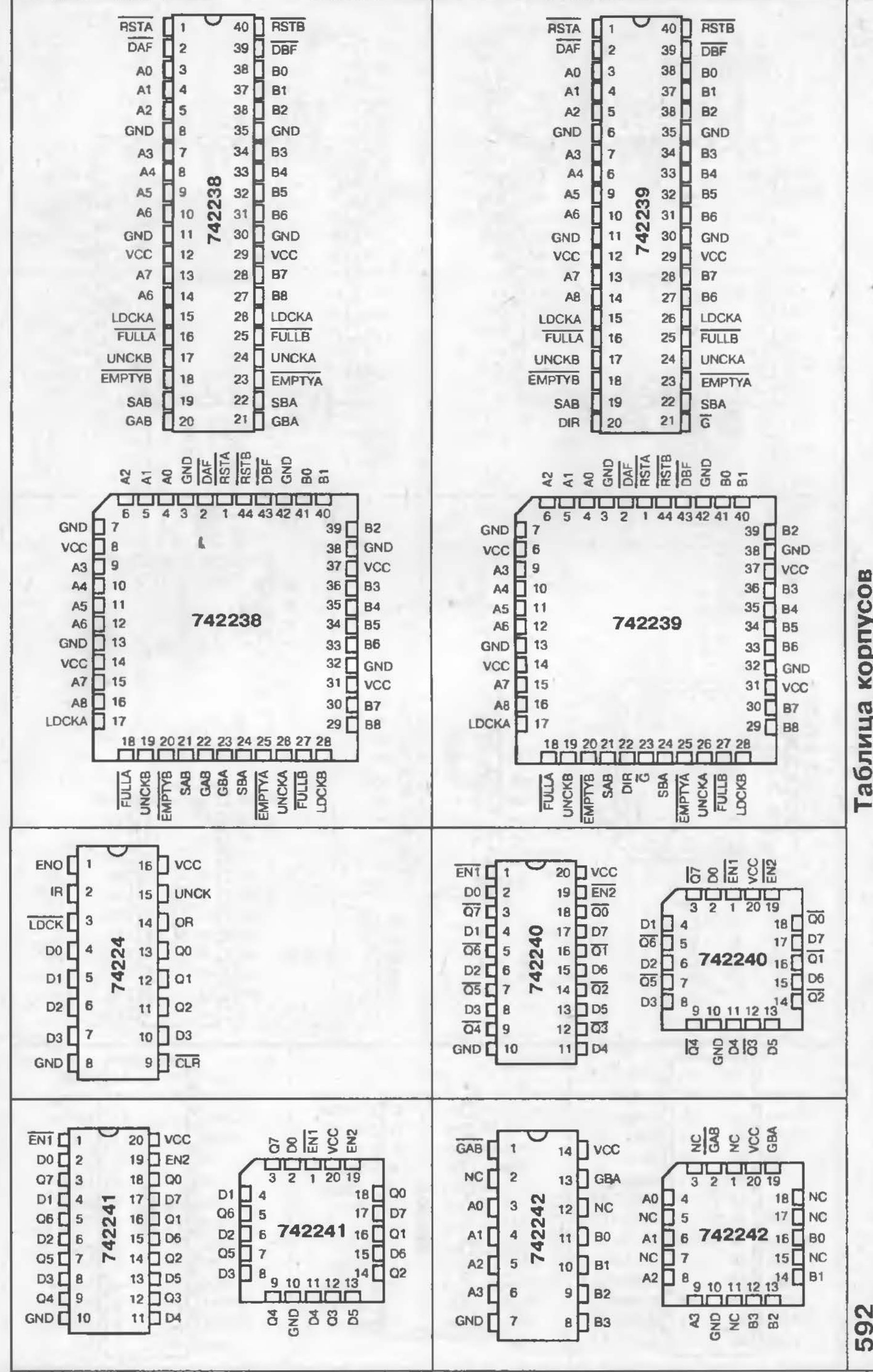
741803: GND 1, NC 2, Q0 3, D0 4, D1 5, Q1 6, GND 7, CLK 8, Q2 9, D2 10, D3 11, Q3 12, NC 13, VCC 14
741804: 5B 1, 6Q 2, 6A 3, 6B 4, VCC 5, 1A 6, 1B 7, 1Q 8, 2A 9, 2B 10, 2Q 11, 3A 12, 3B 13, 3Q 14, GND 15, 4Q 16, 4A 17, 4B 18, 5Q 19, 5A 20
741805: 5B 1, 6Q 2, 6A 3, 6B 4, VCC 5, 1A 6, 1B 7, 1Q 8, 2A 9, 2B 10, 2Q 11, 3A 12, 3B 13, 3Q 14, GND 15, 4Q 16, 4A 17, 4B 18, 5Q 19, 5A 20
741808: 5B 1, 6Q 2, 5A 3, 6B 4, VCC 5, 1A 6, 1B 7, 1Q 8, 2A 9, 2B 10, 2Q 11, 3A 12, 3B 13, 3Q 14, GND 15, 4Q 16, 4A 17, 4B 18, 5Q 19, 5A 20
74181: B0 1, A0 2, S3 3, B2 4, S1 5, S0 6, CYn 7, BA 8, Q0 9, Q1 10, Q2 11, GND 12, Q3 13, A=B 14, P 15, CYn+4 16, G 17, B3 18, A3 19, B2 20, A2 21, B1 22, A1 23, VCC 24
741811: PD 1, VC0 2, XTAL 3, D0 4, D1 5, GND 6, MSCLK 7, RXDAT 8, PRCMP 9, INDX 10, UBB 11, RAWDO 12, EARLY 13, LATE 14, CLK 15, RDDAT 16, WRDAT 17, SYNC 18, PRCLK 19, TXDAT 20, RD/WR 21, NORMAL 22, PU 23, VCC 24
741812: DAT14 1, GND 2, TXENB 3, DAT13 4, DAT12 5, DAT11 6, DAT10 7, DAT9 8, DAT8 9, DAT7 10, SYNC 11, DAT6 12, GND 13, DAT5 14, DAT4 15, DAT3 16, DAT2 17, NC 18, DAT1 19, DAT0 20, CALCEN 21, RESET 22, WRITE 23, VCC 24, EOEN 25, GND 26, NC 27, RSEL0 28, CS 29, READ 30, HCOMPARE 31, RSEL1 32, ZEROS 33, DATERR 34, EQUAL 35, FLAG 36, ECC/CRC 37, GND 38, DMARQ 39, 8/16 40, TXDAT 41, TXCLK 42, INCLK 43, RXI/TXI 44, CALC/SHIFT 45, RXDAT 46, DAT15 47, UBB 48
74182: G1 1, P1 2, G0 3, P0 4, G3 5, P3 6, P 7, GND 8, CYn+z 9, G 10, CYn+y 11, CYn+x 12, CYn 13, G2 14, P2 15, VCC 16
74182: NC 1, G1 2, P1 3, G0 4, P0 5, NC 6, G3 7, P3 8, P 9, GND 10, NC 11, CYn+z 12, G 13, CYn+y 14, CYn+X 15, NC 16, CYn 17, G2 18, P2 19, VCC 20
741821: Q4 1, Q3 2, Q2 3, Q1 4, Q0 5, VCC 6, ENO 7, D0 8, D1 9, D2 10, D3 11, D4 12, D5 13, D6 14, D7 15, D8 15, D9 17, GND 18, CLK 19, Q9 20, Q8 21, Q7 22, Q6 23, Q5 24
741823: Q4 1, Q3 2, Q2 3, Q1 4, Q0 5, VCC 6, ENO 7, D0 8, D1 9, D2 10, D3 11, D4 12, D5 13, D6 14, D7 15, D8 16, CLR 17, GND 18, CLK 19, CLKEN 20, Q8 21, Q7 22, Q6 23, Q5 24
74183: NC 1, 1A 2, NC 3, 1B 4, NC 5, 1CYI 6, NC 7, 1CYO 8, 1SUM 9, GND 10, NC 11, 2SUM 12, NC 13, 2CYD 14, NC 15, 2CYI 16, NC 17, 2B 18, 2A 19, VCC 20
741832: 5B 1, 6Q 2, 5A 3, 6B 4, VCC 5, 1A 6, 1B 7, 1Q 8, 2A 9, 2B 10, 2Q 11, 3A 12, 3B 13, 3Q 14, GND 15, 4Q 16, 4A 17, 4B 18, 5Q 19, 5A 20
74184: Q1 1, Q2 2, Q3 3, Q4 4, Q5 5, Q6 6, Q7 7, GND 8, Q8 9, D1 10, D2 11, D3 12, D4 13, D5 14, EN 15, VCC 16
74185: Q1 1, Q2 2, Q3 3, Q4 4, Q5 5, Q6 6, Q7 7, GND 8, Q8 9, D1 10, D2 11, D3 12, D4 13, D5 14, EN 15, VCC 16
74186: NC 1, NC 2, A0 3, A1 4, A2 5, EN1 6, EN2 7, A3 8, A4 9, A5 10, GND1 11, NC 12, GND2 13, Q8 14, Q7 15, Q6 16, Q5 17, Q4 18, Q3 19, Q2 20, Q1 21, Q0 22, GND 23, VCC 24
74187: A6 1, A5 2, A4 3, A3 4, A0 5, A1 6, A2 7, GND 8, Q3 9, Q2 10, Q1 11, Q0 12, EN1 13, EN2 14, A7 15, VCC 16


74188
Q0 1 16 VCC
Q1 2 15 EN
Q2 3 14 A4
Q3 4 13 A3
Q4 5 12 A2
Q5 6 11 A1
Q6 7 10 A0
GND 8 9 Q7
74189
A0 1 16 VCC
EN 2 15 A1
R/W 3 14 A2
D0 4 13 A3
Q0 5 12 D3
D1 6 11 Q3
Q1 7 10 D2
GND 8 9 Q2
74189
EN 3, A0 2, NC 1, VCC 20, A1 19
R/W 4, D0 5, NC 6, Q0 7, D1 8
18 A2, 17 A3, 16 NC, 15 D3, 14 Q3
Q1 9, GND 10, NC 11, Q2 12, D2 13
741894
ENO 1 28 DIR
B0 2 27 A0
B1 3 26 A1
B2 4 25 A2
B3 5 24 A3
ERR 6 23 A4
GND 7 22 VCC
GND 8 21 VCC
B4 9 20 A5
B5 10 19 A6
B6 11 18 A7
B7 12 17 A8
B8 13 16 ENL
R 14 15 NC
741895
ENO 1 28 DIR
B0 2 27 A0
B1 3 26 A1
B2 4 25 A2
B3 5 24 A3
ERR 6 23 A4
GND 7 22 VCC
GND 8 21 VCC
B4 9 20 A5
B5 10 19 A6
B6 11 18 A7
B7 12 17 A8
B8 13 16 ENL
R 14 15 ENE
741896
ENO 1 28 DIR
B0 2 27 A0
B1 3 26 A1
B2 4 25 A2
B3 5 24 A3
ERR 6 23 A4
GND 7 22 VCC
GND 8 21 VCC
B4 9 20 A5
B5 10 19 A6
B6 11 16 A7
B7 12 17 A8
B8 13 18 CLK
R 14 15 NC
741897
ENO 1 28 DIR
B0 2 27 A0
B1 3 26 A1
B2 4 25 A2
B3 5 24 A3
ERR 6 23 A4
GND 7 22 VCC
GND 8 21 VCC
B4 9 20 A5
B5 10 19 A6
B6 11 18 A7
B7 12 17 A8
B8 13 16 CLK
R 14 15 ENE
7419
1A 1 14 VCC
1Q 2 13 6A
2A 3 12 6Q
2Q 4 11 5A
3A 5 10 5Q
3Q 6 9 4A
GND 7 8 4Q
7419
1Q 3, 1A 2, NC 1, VCC 20, 6A 19
2A 4, NC 5, 2Q 6, NC 7, 3A 8
18 6Q, 17 NC, 16 5A, 15 NC, 14 5Q
3Q 9, GND 10, NC 11, 4Q 12, 4A 13
74190
D1 1 16 VCC
Q1 2 15 D0
Q0 3 14 CLK
CE 4 13 RC
SEL U/D 5 12 CY
Q2 6 11 S
Q3 7 10 D2
GND 8 9 D3
74190
Q1 3, D1 2, NC 1, VCC 20, D0 19
Q0 4, CE 5, NC 6, SEL U/D 7, Q2 8
18 CLK, 17 RC, 16 NC, 15 CY, 14 S
Q3 9, GND 10, NC 11, D3 12, D2 13
74191
D1 1 16 VCC
Q1 2 15 D0
Q0 3 14 CLK
CE 4 13 RC
SEL U/D 5 12 CY
Q2 6 11 S
Q3 7 10 D2
GND 8 9 D3
74191
Q1 3, D1 2, NC 1, VCC 20, D0 19
Q0 4, CE 5, NC 6, SEL U/D 7, Q2 8
18 CLK, 17 RC, 16 NC, 15 CY, 14 S
Q3 9, GND 10, NC 11, D3 12, D2 13
74192
D1 1 16 VCC
Q1 2 15 D0
Q0 3 14 CLR
CLKD 4 13 CYD
CLKU 5 12 CYU
Q2 6 11 S
Q3 7 10 D2
GND 8 9 D3
74193
D1 1 16 VCC
Q1 2 15 D0
Q0 3 14 CLR
CLKD 4 13 CYD
CLKU 5 12 CYU
Q2 6 11 S
Q3 7 10 D2
GND 8 9 D3

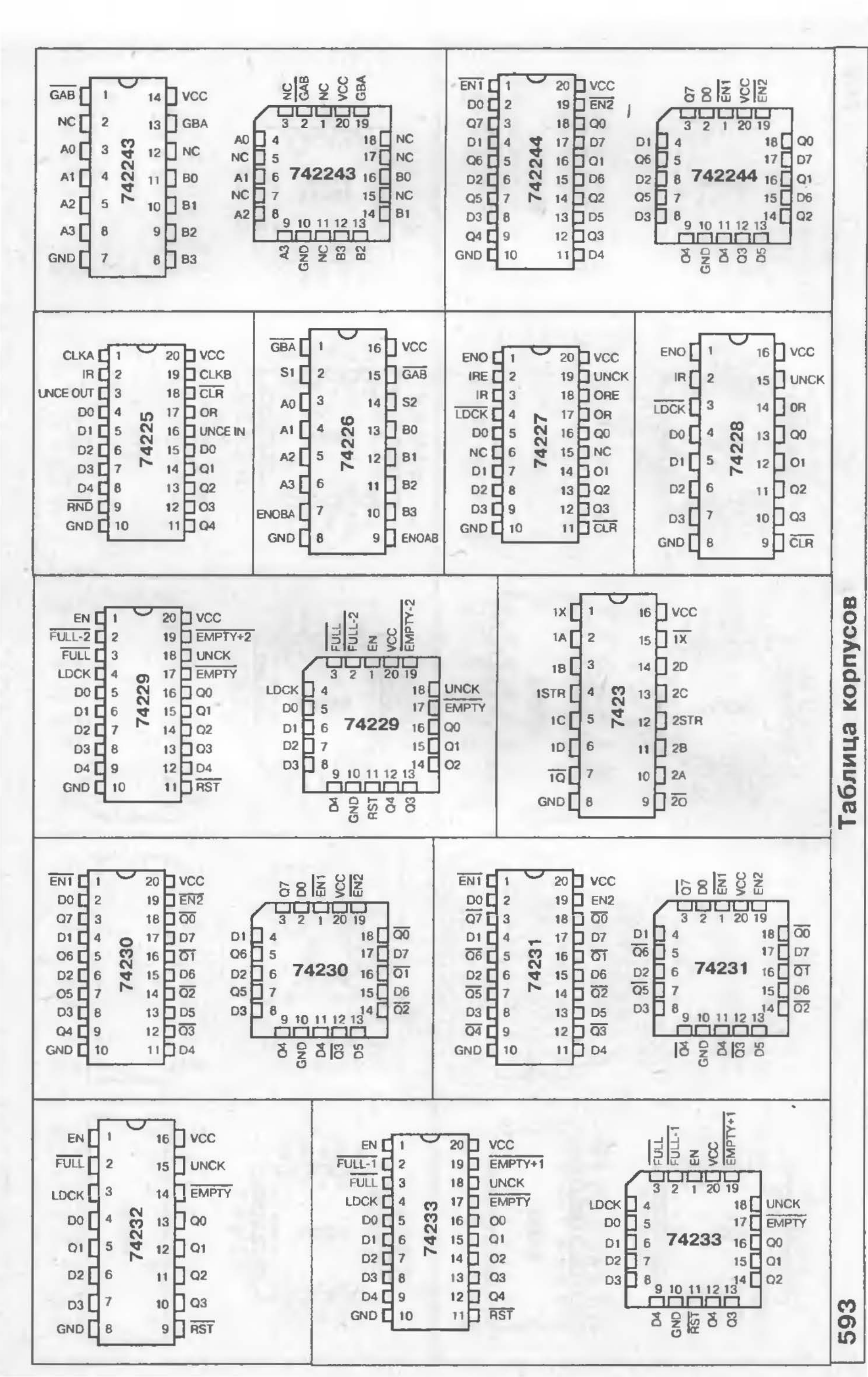

74194
74195
74196
74197
74198
74199
7420
74200
742000
74201
7420/1
74202
7420/2
74206


74207
A6 1 16 VCC
A5 2 15 A7
A4 3 14 WR
A3 4 13 RD
A0 5 12 D0
A1 6 11 D1
A2 7 10 D2
GND 8 9 D3
74208
A0 1 20 VCC
A1 2 19 D3
A2 3 18 A7
A3 4 17 RW
D2 5 16 RD
A4 6 15 Q3
A5 7 14 Q2
A6 8 13 Q1
D1 9 12 Q0
GND 10 11 D0
7421
1A 1 14 VCC
1B 2 13 2D
NC 3 12 2C
1C 4 11 NC
1D 5 10 2B
1Q 6 9 2A
GND 7 8 2Q
7421
1B 1A NC VCC 2D
3 2 1 20 19
NC 4 18 2C
NC 5 17 NC
1C 6 16 NC
NC 7 15 NC
1D 8 14 2B
9 10 11 12 13
1Q GND NC 2Q 2A
7421/1
1A 1 14 VCC
1B 2 13 2D
NC 3 12 2C
1C 4 11 NC
1D 5 10 2B
1Q 6 9 2A
GND 7 8 2Q
7421/1
1B 1A NC VCC 2D
3 2 1 20 19
NC 4 18 2C
NC 5 17 NC
1C 6 16 NC
NC 7 15 NC
1D 8 14 2B
9 10 11 12 13
1Q GND NC 2Q 2A
7421/2
1A 1 14 1B
1Q 2 13 1C
NC 3 12 1D
VCC 4 11 GND
NC 5 10 2Q
2A 6 9 2D
2B 7 8 2C
74214
EN 1 16 VCC
A0 2 15 DATA
A1 3 14 R/W
A2 4 13 A9
A3 5 12 A8
A4 6 11 A7
Q 7 10 A6
GND 8 9 A5
74215
EN 1 16 VCC
A0 2 15 DATA
A1 3 14 R/W
A2 4 13 A9
A3 5 12 A8
A4 6 11 A7
Q 7 10 A6
GND 8 9 A5
74219
A0 1 16 VCC
CS 2 15 A1
R/W 3 14 A2
D0 4 13 A3
Q0 5 12 D3
D1 6 11 Q3
Q1 7 10 D2
GND 8 9 Q2
74219
CB A0 NC VCC A1
3 2 1 20 19
R/W 4 18 A2
D0 5 17 A3
NC 6 16 NC
Q0 7 15 D3
D1 8 14 Q3
9 10 11 12 13
Q1 GND NC Q2 D2
74221
1A 1 16 VCC
1B 2 15 1RCext
1R 3 14 1Cext
1Q 4 13 1Q
2Q 5 12 2Q
2Cext 6 11 2R
2RCext 7 10 2B
GND 8 9 2A
74221
1B 1A NC VCC 1RCext
3 2 1 20 19
1R 4 18 1Cext
1Q 5 17 1Q
NC 6 16 NC
2Q 7 15 2Q
2Cext 8 14 2R
9 10 11 12 13
2RCext GND NC 2A 2B
7422/1
1A 1 14 VCC
1B 2 13 2D
NC 3 12 2C
1C 4 11 NC
1D 5 10 2B
1Q 6 9 2A
GND 7 8 2Q
74222
EN0 1 20 VCC
IRE 2 19 UNCK
IR 3 18 ORE
LDCK 4 17 DR
D0 5 16 Q0
NC 6 15 NC
D1 7 14 Q1
D2 8 13 Q2
D3 9 12 Q3
GND 10 11 CLR
7422/2
1A 1 14 1B
1Q 2 13 1C
NC 3 12 1D
VCC 4 11 GND
NC 5 10 2Q
2A 6 9 2D
2B 7 8 2C
742226
1HF 1 24 1RDCLK
1AF/AE 2 23 1RDEN
1WRCLK 3 22 1OR
1WREN 4 21 1Q
1IR 5 20 2RESET
1D 6 19 VCC
GND 7 16 2D
1RESET 8 17 2IR
2Q 9 16 2WREN
2OR 10 15 2WRCLK
2RDEN 11 14 2AF/AE
2RDCLK 12 13 2HF


742227
1HF 1, 1AF/AE 2, 1WRCLK 3, 1WREN 4, 1IR 5, 1D 6, GND 7, GND 8, 1RESET 9, 2Q 10, 2OR 11, 2RDEN 12, 2RDCLK 13, 2ENO 14
28 1ENO, 27 1RDCLK, 26 1RDEN, 25 1OR, 24 1Q, 23 2RESET, 22 VCC, 21 VCC, 20 2D, 19 2IR, 18 2WREN, 17 2WRCLK, 16 2AF/AE, 15 2HF
742228
1HF 1, 1AF/AE 2, 1WRCLK 3, 1WREN 4, 1IR 5, 1D 6, GND 7, 1RESET 8, 2Q 9, 2OR 10, 2RDEN 11, 2RDCLK 12
24 1RDCLK, 23 1RDEN, 22 1OR, 21 1Q, 20 2RESET, 19 VCC, 18 2D, 17 2IR, 16 2WREN, 15 2WRCLK, 14 2AF/AE, 13 2HF
742229
1HF 1, 1AF/AE 2, 1WRCLK 3, 1WREN 4, 1IR 5, 1D 6, GND 7, GND 8, 1RESET 9, 2Q 10, 2OR 11, 2RDEN 12, 2RDCLK 13, 2ENO 14
28 1ENO, 27 1RDCLK, 26 1RDEN, 26 1OR, 24 1Q, 23 2RESET, 22 VCC, 21 VCC, 20 2D, 19 2IR, 18 2WREN, 17 2WRCLK, 16 2AF/AE, 15 2HF
742232
RST 1, D0 2, D1 3, D2 4, D3 5, VCC 6, D4 7, D5 8, D6 9, D7 10, FULL 11, LDCLK 12
24 EN, 23 Q0, 22 Q1, 21 Q2, 20 Q3, 19 GND, 18 Q4, 17 Q5, 16 Q6, 15 Q7, 14 EMPTY, 13 UNCLK
742232
D1 4, D0 3, RST 2, NC 1, EN 28, Q0 27, Q1 26
D2 5, D3 6, VCC 7, NC 8, D4 9, D5 10, D6 11
25 Q2, 24 Q3, 23 GND, 22 NC, 21 Q4, 20 Q5, 19 Q6
D7 12, FULL 13, LDCLK 14, NC 15, UNCLK 16, EMPTY 17, Q7 18
742233
RST 1, D0 2, D1 3, D2 4, D3 5, VCC 6, D4 7, D5 8, D6 9, D7 10, D8 11, AF/E 12, FULL 13, LDCLK 14
28 EN, 27 Q0, 26 Q1, 25 Q2, 24 Q3, 23 GND, 22 Q4, 21 Q5, 20 Q6, 19 Q7, 18 Q8, 17 HF, 16 EMPTY, 15 UNCLK
742233
D2 4, D1 3, D0 2, RST 1, EN 28, Q0 27, Q1 26
D3 5, VCC 6, D4 7, D5 8, D6 9, D7 10, D8 11
25 Q2, 24 Q3, 23 GND, 22 Q4, 21 Q5, 20 Q6, 19 Q7
AF/E 12, FULL 13, LDCLK 14, UNCLK 15, EMPTY 16, HF 17, Q8 18
742235
A2 6, A1 5, A0 4, GND 3, GBA 2, SBA 1, SAB 44, GAB 43, GND 42, B0 41, B1 40
A3 7, A4 8, VCC 9, A5 10, A6 11, A7 12, A8 13, GND 14, AF/AEA 15, HFA 16, LDCKA 17
39 B2, 38 B3, 37 B4, 36 VCC, 35 B5, 34 B6, 33 B7, 32 B8, 31 VCC, 30 AF/AEB, 29 HFB
FULLA 18, UNCKB 19, EMPTYB 20, DAF 21, RSTA 22, RSTB 23, DFB 24, EMPTYA 25, UNCKA 26, FULLB 27, LDCKB 28
742236
A2 6, A1 5, A0 4, GND 3, G 2, SBA 1, SAB 44, DIR 43, GND 42, B0 41, B1 40
A3 7, A4 8, VCC 9, A5 10, A6 11, A7 12, A8 13, GND 14, AF/AEA 15, HFA 16, LDCKA 17
39 B2, 38 B3, 37 B4, 36 VCC, 35 B5, 34 B6, 33 B7, 32 B8, 31 VCC, 30 AF/AEB, 29 HFB
FULLA 18, UNCKB 19, EMPTYB 20, DAF 21, RSTA 22, RSTB 23, DFB 24, EMPTYA 25, UNCKA 26, FULLB 27, LDCKB 28



742238
RSTA 1, DAF 2, A0 3, A1 4, A2 5, GND 8, A3 7, A4 8, A5 9, A6 10, GND 11, VCC 12, A7 13, A6 14, LDCKA 15, FULLA 16, UNCKB 17, EMPTYB 18, SAB 19, GAB 20
40 RSTB, 39 DBF, 38 B0, 37 B1, 38 B2, 35 GND, 34 B3, 33 B4, 32 B5, 31 B6, 30 GND, 29 VCC, 28 B7, 27 B8, 26 LDCKA, 25 FULLB, 24 UNCKA, 23 EMPTYA, 22 SBA, 21 GBA
742239
RSTA 1, DAF 2, A0 3, A1 4, A2 5, GND 6, A3 7, A4 6, A5 9, A6 10, GND 11, VCC 12, A7 13, A8 14, LDCKA 15, FULLA 16, UNCKB 17, EMPTYB 18, SAB 19, DIR 20
40 RSTB, 39 DBF, 38 B0, 37 B1, 38 B2, 35 GND, 34 B3, 33 B4, 32 B5, 31 B6, 30 GND, 29 VCC, 28 B7, 27 B6, 26 LDCKA, 25 FULLB, 24 UNCKA, 23 EMPTYA, 22 SBA, 21 G
742238
A2 6, A1 5, A0 4, GND 3, DAF 2, RSTA 1, RSTB 44, DBF 43, GND 42, B0 41, B1 40
GND 7, VCC 8, A3 9, A4 10, A5 11, A6 12, GND 13, VCC 14, A7 15, A8 16, LDCKA 17
39 B2, 38 GND, 37 VCC, 36 B3, 35 B4, 34 B5, 33 B6, 32 GND, 31 VCC, 30 B7, 29 B8
FULLA 18, UNCKB 19, EMPTYB 20, SAB 21, GAB 22, GBA 23, SBA 24, EMPTYA 25, UNCKA 26, FULLB 27, LDCKB 28
742239
A2 6, A1 5, A0 4, GND 3, DAF 2, RSTA 1, RSTB 44, DBF 43, GND 42, B0 41, B1 40
GND 7, VCC 6, A3 9, A4 10, A5 11, A6 12, GND 13, VCC 14, A7 15, A8 16, LDCKA 17
39 B2, 38 GND, 37 VCC, 36 B3, 35 B4, 34 B5, 33 B6, 32 GND, 31 VCC, 30 B7, 29 B8
FULLA 18, UNCKB 19, EMPTYB 20, SAB 21, DIR 22, G 23, SBA 24, EMPTYA 25, UNCKA 26, FULLB 27, LDCKB 28
74224
ENO 1, IR 2, LDCK 3, D0 4, D1 5, D2 6, D3 7, GND 8
16 VCC, 15 UNCK, 14 OR, 13 Q0, 12 Q1, 11 Q2, 10 D3, 9 CLR
742240
EN1 1, D0 2, Q7 3, D1 4, Q6 5, D2 6, Q5 7, D3 8, Q4 9, GND 10
20 VCC, 19 EN2, 18 Q0, 17 D7, 16 Q1, 15 D6, 14 Q2, 13 D5, 12 Q3, 11 D4
742240
Q7 3, D0 2, EN1 1, VCC 20, EN2 19
D1 4, Q6 5, D2 6, Q5 7, D3 8
18 Q0, 17 D7, 16 Q1, 15 D6, 14 Q2
Q4 9, GND 10, D4 11, Q3 12, D5 13
742241
EN1 1, D0 2, Q7 3, D1 4, Q6 5, D2 6, Q5 7, D3 8, Q4 9, GND 10
20 VCC, 19 EN2, 18 Q0, 17 D7, 16 Q1, 15 D6, 14 Q2, 13 D5, 12 Q3, 11 D4
742241
Q7 3, D0 2, EN1 1, VCC 20, EN2 19
D1 4, Q6 5, D2 6, Q5 7, D3 8
18 Q0, 17 D7, 16 Q1, 15 D6, 14 Q2
Q4 9, GND 10, D4 11, Q3 12, D5 13
742242
GAB 1, NC 2, A0 3, A1 4, A2 5, A3 6, GND 7
14 VCC, 13 GBA, 12 NC, 11 B0, 10 B1, 9 B2, 8 B3
742242
NC 3, GAB 2, NC 1, VCC 20, GBA 19
A0 4, NC 5, A1 6, NC 7, A2 8
18 NC, 17 NC, 16 B0, 15 NC, 14 B1
A3 9, GND 10, NC 11, B3 12, B2 13


742243 (DIP): GAB 1, NC 2, A0 3, A1 4, A2 5, A3 6, GND 7, B3 8, B2 9, B1 10, B0 11, NC 12, GBA 13, VCC 14
742243 (PLCC): NC 3, GAB 2, NC 1, VCC 20, GBA 19, A0 4, NC 5, A1 6, NC 7, A2 8, NC 18, NC 17, B0 16, NC 15, B1 14, A3 9, GND 10, NC 11, B3 12, B2 13
742244 (DIP): EN1 1, D0 2, Q7 3, D1 4, Q6 5, D2 6, Q5 7, D3 8, Q4 9, GND 10, D4 11, Q3 12, D5 13, Q2 14, D6 15, Q1 16, D7 17, Q0 18, EN2 19, VCC 20
742244 (PLCC): Q7 3, D0 2, EN1 1, VCC 20, EN2 19, D1 4, Q6 5, D2 6, Q5 7, D3 8, Q0 18, D7 17, Q1 16, D6 15, Q2 14, Q4 9, GND 10, D4 11, Q3 12, D5 13
74225: CLKA 1, IR 2, UNCE OUT 3, D0 4, D1 5, D2 6, D3 7, D4 8, RND 9, GND 10, Q4 11, O3 12, Q2 13, Q1 14, D0 15, UNCE IN 16, OR 17, CLR 18, CLKB 19, VCC 20
74226: GBA 1, S1 2, A0 3, A1 4, A2 5, A3 6, ENOBA 7, GND 8, ENOAB 9, B3 10, B2 11, B1 12, B0 13, S2 14, GAB 15, VCC 16
74227: ENO 1, IRE 2, IR 3, LDCK 4, D0 5, NC 6, D1 7, D2 8, D3 9, GND 10, CLR 11, Q3 12, Q2 13, O1 14, NC 15, Q0 16, OR 17, ORE 18, UNCK 19, VCC 20
74228: ENO 1, IR 2, LDCK 3, D0 4, D1 5, D2 6, D3 7, GND 8, CLR 9, Q3 10, Q2 11, O1 12, Q0 13, 0R 14, UNCK 15, VCC 16
74229 (DIP): EN 1, FULL-2 2, FULL 3, LDCK 4, D0 5, D1 6, D2 7, D3 8, D4 9, GND 10, RST 11, D4 12, Q3 13, Q2 14, Q1 15, Q0 16, EMPTY 17, UNCK 18, EMPTY+2 19, VCC 20
74229 (PLCC): FULL 3, FULL-2 2, EN 1, VCC 20, EMPTY-2 19, LDCK 4, D0 5, D1 6, D2 7, D3 8, UNCK 18, EMPTY 17, Q0 16, Q1 15, O2 14, D4 9, GND 10, RST 11, Q4 12, Q3 13
7423: 1X 1, 1A 2, 1B 3, 1STR 4, 1C 5, 1D 6, 1Q 7, GND 8, 2O 9, 2A 10, 2B 11, 2STR 12, 2C 13, 2D 14, 1X 15, VCC 16
74230 (DIP): EN1 1, D0 2, Q7 3, D1 4, Q6 5, D2 6, O5 7, D3 8, Q4 9, GND 10, D4 11, Q3 12, D5 13, Q2 14, D6 15, Q1 16, D7 17, Q0 18, EN2 19, VCC 20
74230 (PLCC): Q7 3, D0 2, EN1 1, VCC 20, EN2 19, D1 4, Q6 5, D2 6, Q5 7, D3 8, Q0 18, D7 17, Q1 16, D6 15, Q2 14, Q4 9, GND 10, D4 11, Q3 12, D5 13
74231 (DIP): EN1 1, D0 2, Q7 3, D1 4, Q6 5, D2 6, Q5 7, D3 8, Q4 9, GND 10, D4 11, Q3 12, D5 13, Q2 14, D6 15, Q1 16, D7 17, Q0 18, EN2 19, VCC 20
74231 (PLCC): Q7 3, D0 2, EN1 1, VCC 20, EN2 19, D1 4, Q6 5, D2 6, Q5 7, D3 8, Q0 18, D7 17, Q1 16, D6 15, Q2 14, Q4 9, GND 10, D4 11, Q3 12, D5 13
74232: EN 1, FULL 2, LDCK 3, D0 4, Q1 5, D2 6, D3 7, GND 8, RST 9, Q3 10, Q2 11, Q1 12, Q0 13, EMPTY 14, UNCK 15, VCC 16
74233 (DIP): EN 1, FULL-1 2, FULL 3, LDCK 4, D0 5, D1 6, D2 7, D3 8, D4 9, GND 10, RST 11, Q4 12, Q3 13, O2 14, Q1 15, O0 16, EMPTY 17, UNCK 18, EMPTY+1 19, VCC 20
74233 (PLCC): FULL 3, FULL-1 2, EN 1, VCC 20, EMPTY+1 19, LDCK 4, D0 5, D1 6, D2 7, D3 8, UNCK 18, EMPTY 17, Q0 16, Q1 15, Q2 14, D4 9, GND 10, RST 11, Q4 12, Q3 13

74234

DIP		PLCC	
1	$\overline{EN}$	1	NC
2	IR	2	$\overline{EN}$
3	SI	3	IR
4	D0	4	SI
5	D1	5	D0
6	D2	6	NC
7	D3	7	D1
8	GND	8	D2
9	$\overline{RST}$	9	D3
10	Q3	10	GND
11	Q2	11	NC
12	Q1	12	$\overline{RST}$
13	Q0	13	Q3
14	OR	14	Q2
15	SO	15	O1
16	VCC	16	NC
		17	Q0
		18	OR
		19	SO
		20	VCC

74235

DIP		PLCC	
1	$\overline{EN}$	1	$\overline{EN}$
2	HF	2	HF
3	IR	3	IR
4	SI	4	SI
5	D0	5	D0
6	D1	8	D1
7	D2	7	D2
8	D3	8	D3
9	D4	9	D4
10	GND	10	GND
11	$\overline{RST}$	11	$\overline{RST}$
12	Q4	12	Q4
13	Q3	13	Q3
14	Q2	14	Q2
15	Q1	15	Q1
16	Q0	16	Q0
17	OR	17	OR
18	SO	18	SO
19	$\overline{AF}$/E	19	AF/E
20	VCC	20	VCC

74236

DIP		PLCC	
1	NC	1	NC
2	IR	2	NC
3	SI	3	IR
4	D0	4	SI
5	D1	5	D0
6	D2	6	NC
7	D3	7	D1
8	GND	8	D2
9	$\overline{RST}$	9	D3
10	Q3	10	GND
11	Q2	11	NC
12	Q1	12	$\overline{RST}$
13	Q0	13	Q3
14	OR	14	Q2
15	SO	15	Q1
16	VCC	16	NC
		17	Q0
		18	OR
		19	SO
		20	VCC

74237

DIP		PLCC	
1	A0	1	NC
2	A1	2	A0
3	A2	3	A1
4	$\overline{ENL}$	4	A2
5	$\overline{EN2}$	5	$\overline{ENL}$
6	EN1	8	$\overline{NC}$
7	O7	7	$\overline{EN2}$
6	GND	8	EN1
9	Q6	9	Q7
10	Q5	10	GND
11	Q4	11	NC
12	Q3	12	Q6
13	Q2	13	Q5
14	Q1	14	Q4
15	Q0	15	Q3
16	VCC	16	NC
		17	Q2
		18	Q1
		19	Q0
		20	VCC

74238

DIP		PLCC	
1	A0	1	NC
2	A1	2	A0
3	A2	3	A1
4	$\overline{EN2}$	4	A2
5	$\overline{EN3}$	5	$\overline{EN2}$
6	EN1	6	$\overline{NC}$
7	Q7	7	$\overline{EN3}$
6	GND	6	EN1
9	Q6	9	Q7
10	Q5	10	GND
11	Q4	11	NC
12	Q3	12	Q6
13	Q2	13	Q5
14	O1	14	Q4
15	Q0	15	Q3
16	VCC	16	NC
		17	O2
		18	Q1
		19	Q0
		20	VCC

74239

DIP		PLCC	
1	$\overline{1EN}$	1	NC
2	1A0	2	$\overline{1EN}$
3	1A1	3	1A0
4	1Q0	4	1A1
5	1Q1	5	1Q0
6	1Q2	6	NC
7	1Q3	7	1Q1
8	GND	8	1Q2
9	2Q3	9	1Q3
10	2Q2	10	GND
11	2Q1	11	NC
12	2Q0	12	2Q3
13	2A1	13	2Q2
14	2A0	14	2Q1
15	$\overline{2EN}$	15	2Q0
16	VCC	16	NC
		17	2A1
		18	2A0
		19	$\overline{2EN}$
		20	VCC

7424

DIP		PLCC	
1	1B	1	NC
2	1A	2	1B
3	$\overline{1Q}$	3	1A
4	2B	4	$\overline{1Q}$
5	2A	5	NC
6	$\overline{2O}$	6	2B
7	GND	7	NC
6	$\overline{3Q}$	6	2A
9	3A	9	$\overline{2O}$
10	3B	10	GND
11	$\overline{4Q}$	11	NC
12	4A	12	$\overline{3Q}$
13	4B	13	3A
14	VCC	14	3B
		15	NC
		16	$\overline{4Q}$
		17	NC
		16	4A
		19	4B
		20	VCC

74240

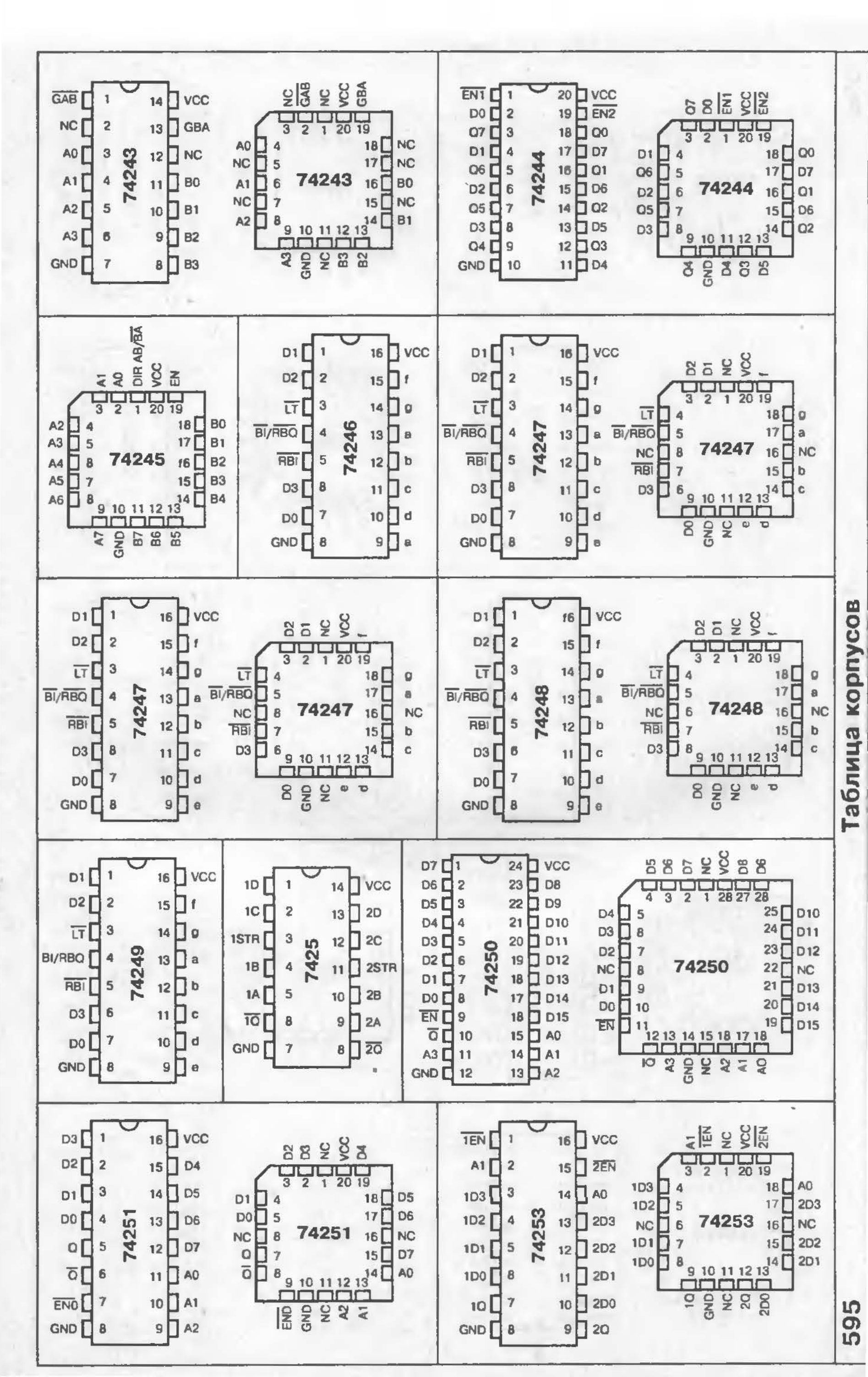
DIP		PLCC	
1	$\overline{EN1}$	I	$\overline{EN1}$
2	D0	2	D0
3	$\overline{Q7}$	3	$\overline{Q7}$
4	D1	4	D1
5	$\overline{Q6}$	5	$\overline{Q6}$
8	D2	6	D2
7	$\overline{Q5}$	7	$\overline{Q5}$
8	D3	8	D3
9	$\overline{Q4}$	9	$\overline{Q4}$
10	GND	10	GND
11	D4	11	D4
12	$\overline{Q3}$	12	$\overline{Q3}$
13	D5	13	D5
14	$\overline{Q2}$	14	$\overline{Q2}$
15	D6	15	D6
16	$\overline{O1}$	16	$\overline{Q1}$
17	D7	17	D7
18	$\overline{O0}$	18	$\overline{D0}$
19	$\overline{EN2}$	19	$\overline{EN2}$
20	VCC	20	VCC

74241

DIP		PLCC	
1	$\overline{EN1}$	1	$\overline{EN1}$
2	D0	2	D0
3	Q7	3	Q7
4	D1	4	D1
5	Q6	5	Q6
6	D2	6	D2
7	Q5	7	Q5
8	D3	8	D3
9	Q4	9	Q4
10	GND	10	GND
11	D4	11	D4
12	Q3	12	Q3
13	D5	13	D5
14	Q2	14	Q2
15	D6	15	D6
16	Q1	16	Q1
17	D7	17	D7
18	Q0	18	Q0
19	EN2	19	EN2
20	VCC	20	VCC

74242

DIP		PLCC	
1	$\overline{GAB}$	1	NC
2	NC	2	$\overline{GAB}$
3	A0	3	NC
4	A1	4	A0
5	A2	5	NC
6	A3	6	A1
7	GND	7	NC
8	B3	8	A2
9	B2	9	A3
10	B1	10	GND
11	B0	11	NC
12	NC	12	B3
13	GBA	13	B2
14	VCC	14	B1
		15	NC
		16	B0
		17	NC
		16	NC
		19	GBA
		20	VCC


74243
GAB 1 14 VCC
NC 2 13 GBA
A0 3 12 NC
A1 4 11 B0
A2 5 10 B1
A3 6 9 B2
GND 7 8 B3
74243
NC GAB NC VCC GBA
3 2 1 20 19
A0 4 18 NC
NC 5 17 NC
A1 6 16 B0
NC 7 15 NC
A2 8 14 B1
9 10 11 12 13
A3 GND NC B3 B2
74244
EN1 1 20 VCC
D0 2 19 EN2
Q7 3 18 Q0
D1 4 17 D7
Q6 5 16 Q1
D2 6 15 D6
Q5 7 14 Q2
D3 8 13 D5
Q4 9 12 Q3
GND 10 11 D4
74244
Q7 D0 EN1 VCC EN2
3 2 1 20 19
D1 4 18 Q0
Q6 5 17 D7
D2 6 16 Q1
Q5 7 15 D6
D3 8 14 Q2
9 10 11 12 13
Q4 GND D4 Q3 D5
74245
A1 A0 DIR AB/BA VCC EN
3 2 1 20 19
A2 4 18 B0
A3 5 17 B1
A4 6 16 B2
A5 7 15 B3
A6 8 14 B4
9 10 11 12 13
A7 GND B7 B6 B5
74246
D1 1 16 VCC
D2 2 15 f
LT 3 14 g
BI/RBQ 4 13 a
RBI 5 12 b
D3 6 11 c
D0 7 10 d
GND 8 9 e
74247
D1 1 16 VCC
D2 2 15 f
LT 3 14 g
BI/RBQ 4 13 a
RBI 5 12 b
D3 6 11 c
D0 7 10 d
GND 8 9 e
74247
D2 D1 NC VCC f
3 2 1 20 19
LT 4 18 g
BI/RBQ 5 17 a
NC 6 16 NC
RBI 7 15 b
D3 8 14 c
9 10 11 12 13
D0 GND NC e d
74247
D1 1 16 VCC
D2 2 15 f
LT 3 14 g
BI/RBQ 4 13 a
RBI 5 12 b
D3 6 11 c
D0 7 10 d
GND 8 9 e
74247
D2 D1 NC VCC f
3 2 1 20 19
LT 4 18 g
BI/RBQ 5 17 a
NC 6 16 NC
RBI 7 15 b
D3 8 14 c
9 10 11 12 13
D0 GND NC e d
74248
D1 1 16 VCC
D2 2 15 f
LT 3 14 g
BI/RBQ 4 13 a
RBI 5 12 b
D3 6 11 c
D0 7 10 d
GND 8 9 e
74248
D2 D1 NC VCC f
3 2 1 20 19
LT 4 18 g
BI/RBQ 5 17 a
NC 6 16 NC
RBI 7 15 b
D3 8 14 c
9 10 11 12 13
D0 GND NC e d
74249
D1 1 16 VCC
D2 2 15 f
LT 3 14 g
BI/RBQ 4 13 a
RBI 5 12 b
D3 6 11 c
D0 7 10 d
GND 8 9 e
7425
1D 1 14 VCC
1C 2 13 2D
1STR 3 12 2C
1B 4 11 2STR
1A 5 10 2B
1Q 6 9 2A
GND 7 8 2Q
74250
D7 1 24 VCC
D6 2 23 D8
D5 3 22 D9
D4 4 21 D10
D3 5 20 D11
D2 6 19 D12
D1 7 18 D13
D0 8 17 D14
EN 9 16 D15
Q 10 15 A0
A3 11 14 A1
GND 12 13 A2
74250
D5 D6 D7 NC VCC D8 D6
4 3 2 1 28 27 26
D4 5 25 D10
D3 6 24 D11
D2 7 23 D12
NC 8 22 NC
D1 9 21 D13
D0 10 20 D14
EN 11 19 D15
12 13 14 15 16 17 18
Q A3 GND NC A2 A1 A0
74251
D3 1 16 VCC
D2 2 15 D4
D1 3 14 D5
D0 4 13 D6
Q 5 12 D7
Q 6 11 A0
EN0 7 10 A1
GND 8 9 A2
74251
D2 D3 NC VCC D4
3 2 1 20 19
D1 4 18 D5
D0 5 17 D6
NC 6 16 NC
Q 7 15 D7
Q 8 14 A0
9 10 11 12 13
END GND NC A2 A1
74253
1EN 1 16 VCC
A1 2 15 2EN
1D3 3 14 A0
1D2 4 13 2D3
1D1 5 12 2D2
1D0 6 11 2D1
1Q 7 10 2D0
GND 8 9 2Q
74253
A1 1EN NC VCC 2EN
3 2 1 20 19
1D3 4 18 A0
1D2 5 17 2D3
NC 6 16 NC
1D1 7 15 2D2
1D0 8 14 2D1
9 10 11 12 13
1Q GND NC 2Q 2D0

742540

DIP			
1	$\overline{EN1}$	20	VCC
2	D0	19	$\overline{EN2}$
3	D1	18	$\overline{Q0}$
4	D2	17	$\overline{Q1}$
5	D3	16	$\overline{Q2}$
6	D4	15	$\overline{Q3}$
7	D5	14	$\overline{Q4}$
8	D6	13	$\overline{Q5}$
9	D7	12	$\overline{Q6}$
10	GND	11	$\overline{Q7}$

PLCC 742540	
3	D1
2	D0
1	$\overline{EN1}$
20	VCC
19	$\overline{EN2}$
4	D2
5	D3
6	D4
7	D5
8	D5
18	$\overline{D0}$
17	$\overline{Q1}$
16	$\overline{Q2}$
15	$\overline{Q3}$
14	$\overline{Q4}$
9	D7
10	GND
11	$\overline{Q7}$
12	$\overline{Q6}$
13	$\overline{Q5}$

742541

DIP			
1	$\overline{EN1}$	20	VCC
2	D0	19	$\overline{EN2}$
3	D1	18	Q0
4	D2	17	Q1
5	D3	16	Q2
6	D4	15	Q3
7	D5	14	Q4
8	D5	13	Q5
9	D7	12	Q6
10	GND	11	Q7

PLCC 742541	
3	D1
2	D0
1	$\overline{EN1}$
20	VCC
19	$\overline{EN2}$
4	D2
5	D3
6	D4
7	D5
8	D6
18	Q0
17	Q1
16	Q2
15	Q3
14	Q4
9	D7
10	GND
11	Q7
12	Q6
13	Q5

74256

DIP			
1	A0	16	VCC
2	A1	15	$\overline{CLR}$
3	1D	14	$\overline{EN}$
4	1Q0	13	2D
5	1Q1	12	2Q3
6	1Q2	11	2Q2
7	1Q3	10	2Q1
8	GND	9	2Q0

PLCC 74256	
3	A1
2	A0
1	NC
20	VCC
19	$\overline{CLR}$
4	1D
5	1Q0
6	NC
7	1Q1
8	1Q2
18	$\overline{EN}$
17	2D
18	NC
15	2Q3
14	2Q2
9	1Q3
10	GND
11	NC
12	2Q0
13	2Q1

74257

DIP			
1	SEL $\overline{A}$/B	16	VCC
2	1A	15	$\overline{EN}$
3	1B	14	4A
4	1Q	13	4B
5	2A	12	4Q
6	2B	11	3A
7	2Q	10	3B
8	GND	9	3Q

PLCC 74257	
3	1A
2	SEL $\overline{A}$/B
1	NC
20	VCC
19	$\overline{EN}$
4	1B
5	1Q
6	NC
7	2A
8	2B
18	4A
17	4B
16	NC
15	4Q
14	3A
9	2Q
10	GND
11	NC
12	3Q
13	3B

74258

DIP			
1	SEL $\overline{A}$/B	16	VCC
2	1A	15	$\overline{EN}$
3	1B	14	4A
4	$\overline{1Q}$	13	4B
5	2A	12	$\overline{4Q}$
6	2B	11	3A
7	$\overline{2Q}$	10	3B
8	GND	9	$\overline{3Q}$

PLCC 74258	
3	1A
2	SEL $\overline{A}$/B
1	NC
20	VCC
19	$\overline{EN}$
4	1B
5	$\overline{1Q}$
6	NC
7	2A
8	2B
18	4A
17	4B
16	NC
15	$\overline{4Q}$
14	3A
9	$\overline{2Q}$
10	GND
11	NC
12	$\overline{3Q}$
13	3B

74259

DIP			
1	A0	16	VCC
2	A1	15	$\overline{CLR}$
3	A2	14	$\overline{EN}$
4	Q0	13	D
5	Q1	12	Q7
6	Q2	11	Q6
7	Q3	10	Q5
8	GND	9	Q4

PLCC 74259	
3	1A
2	A0
1	NC
20	VCC
19	$\overline{CLR}$
4	A2
5	Q0
6	NC
7	Q1
8	Q2
18	$\overline{EN}$
17	D
16	NC
15	Q7
14	Q6
9	$\overline{Q3}$
10	GND
11	NC
12	$\overline{Q4}$
13	Q5

7426

DIP			
1	1B	14	VCC
2	1A	13	4B
3	$\overline{1Q}$	12	4A
4	2B	11	$\overline{4Q}$
5	2A	10	3B
6	$\overline{2Q}$	9	3A
7	GND	8	$\overline{3Q}$

PLCC 7426	
3	1A
2	1B
1	NC
20	VCC
19	4B
4	$\overline{1Q}$
5	NC
6	2B
7	NC
8	2A
18	4A
17	NC
16	$\overline{4Q}$
15	NC
14	3B
9	$\overline{2Q}$
10	GND
11	NC
12	$\overline{3Q}$
13	3A

74260

DIP			
1	1C	14	VCC
2	1D	13	1B
3	1E	12	1A
4	2A	11	2B
5	$\overline{1Q}$	10	2C
6	$\overline{2Q}$	9	2D
7	GND	8	2E

PLCC 74260	
3	1D
2	1C
1	NC
20	VCC
19	1B
4	1E
5	NC
6	2A
7	NC
8	$\overline{1Q}$
18	1A
17	NC
16	NC
15	2B
14	2C
9	$\overline{2Q}$
10	GND
11	NC
12	2E
13	2D

74261

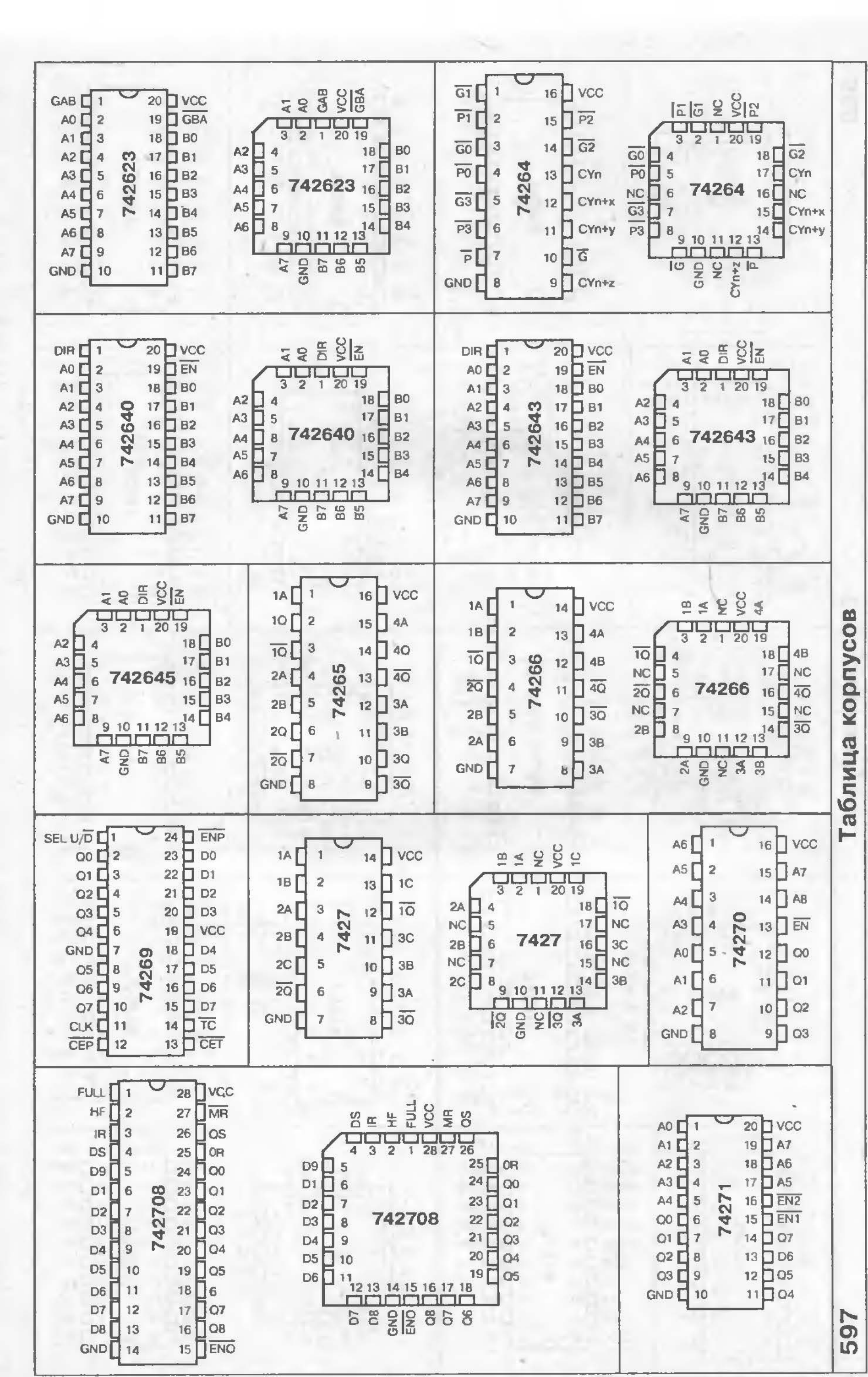
DIP			
1	B3	16	VCC
2	B4	15	B2
3	C	14	B1
4	M2	13	B0
5	$\overline{Q4}$	12	M1
6	Q3	11	M0
7	Q2	10	Q0
8	GND	9	Q1

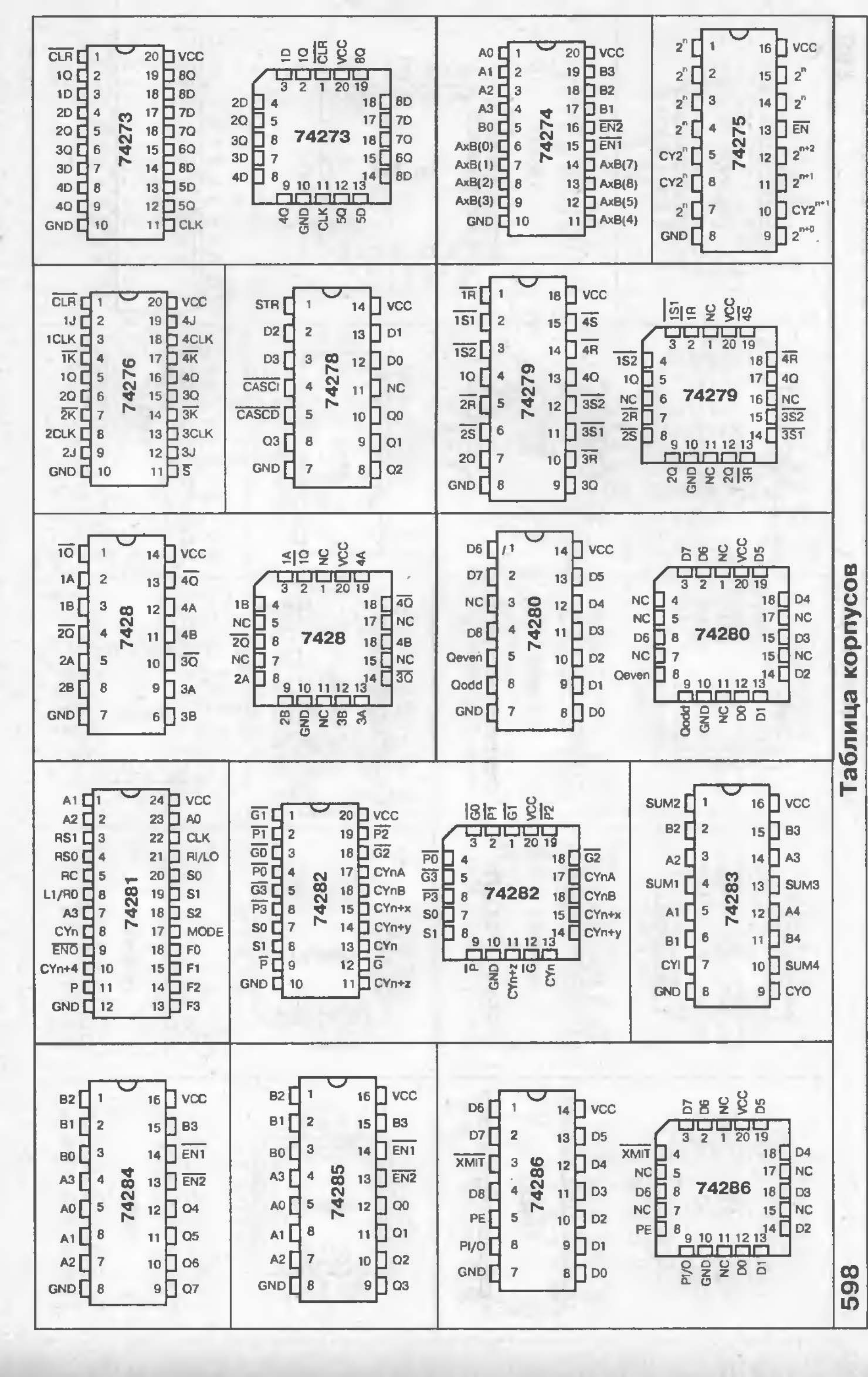
PLCC 74261	
3	B4
2	B3
1	NC
20	VCC
19	B2
4	C
5	M2
6	NC
7	$\overline{Q4}$
8	Q3
18	B1
17	B0
16	NC
15	M1
14	M0
9	Q2
10	GND
11	NC
12	Q1
13	Q0

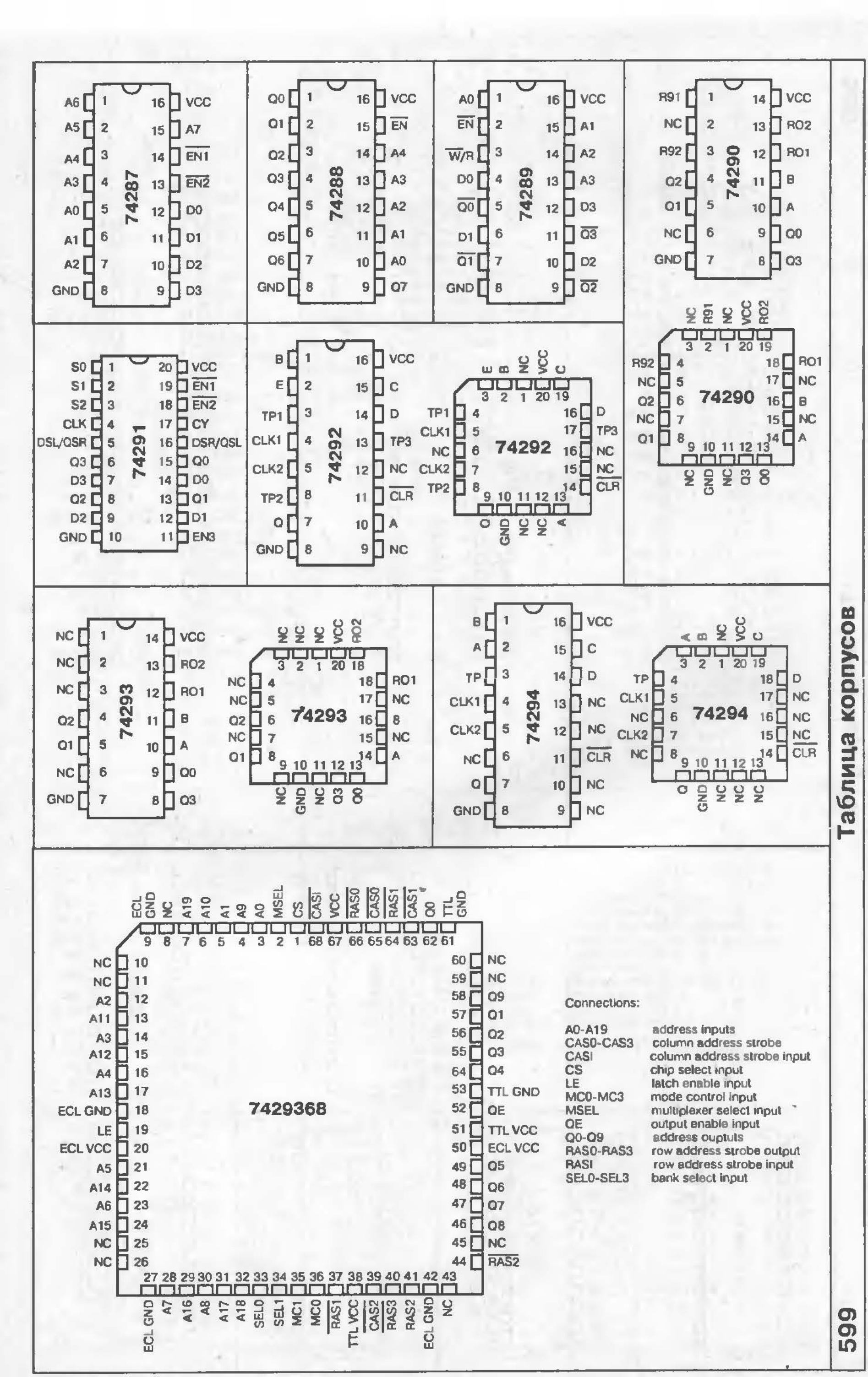
742620

DIP			
1	GAB	20	VCC
2	A0	19	$\overline{GBA}$
3	A1	18	B0
4	A2	17	B1
5	A3	16	B2
6	A4	15	B3
7	A5	14	B4
8	A6	13	B5
9	A7	12	B6
10	GND	11	B7

PLCC 742620	
3	A1
2	A0
1	GAB
20	VCC
19	$\overline{GBA}$
4	A2
5	A3
8	A4
7	A5
8	A6
18	B0
17	B1
16	B2
15	B3
14	B4
9	A7
10	GND
11	B7
12	B6
13	B5


742623
742623
74264
74264
742640
742640
742643
742643
742645
74265
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74266
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742708
742708
74271


74273
CLR 1Q 1D 2D 2Q 3Q 3D 4D 4Q GND CLK 5Q 5D 8D 6Q 7Q 7D 8D 8Q VCC
74273
1D 1Q CLR VCC 8Q 2D 2Q 3Q 3D 4D 4Q GND CLK 5Q 5D 8D 6Q 7Q 7D 8D
74274
A0 A1 A2 A3 B0 AxB(0) AxB(1) AxB(2) AxB(3) GND AxB(4) AxB(5) AxB(8) AxB(7) EN1 EN2 B1 B2 B3 VCC
74275
2n 2n 2n 2n CY2n CY2n 2n GND 2n+0 CY2n+1 2n+1 2n+2 EN 2n 2n VCC
74276
CLR 1J 1CLK 1K 1Q 2Q 2K 2CLK 2J GND S 3J 3CLK 3K 3Q 4Q 4K 4CLK 4J VCC
74278
STR D2 D3 CASCI CASCD Q3 GND Q2 Q1 Q0 NC D0 D1 VCC
74279
1R 1S1 1S2 1Q 2R 2S 2Q GND 3Q 3R 3S1 3S2 4Q 4R 4S VCC
74279
1S1 1R NC VCC 4S 1S2 1Q NC 2R 2S 2Q GND NC 2Q 3R 3S1 3S2 NC 4Q 4R
7428
1Q 1A 1B 2Q 2A 2B GND 3B 3A 3Q 4B 4A 4Q VCC
7428
1A 1Q NC VCC 4A 1B NC 2Q NC 2A 2B GND NC 3B 3A 3Q NC 4B NC 4Q
74280
D6 D7 NC D8 Qeven Qodd GND D0 D1 D2 D3 D4 D5 VCC
74280
D7 D6 NC VCC D5 NC NC D6 NC Qeven Qodd GND NC D0 D1 D2 NC D3 NC D4
74281
A1 A2 RS1 RS0 RC L1/R0 A3 CYn ENO CYn+4 P GND F3 F2 F1 F0 MODE S2 S1 S0 RI/LO CLK A0 VCC
74282
G1 P1 G0 P0 G3 P3 S0 S1 P GND CYn+z G CYn CYn+y CYn+x CYnB CYnA G2 P2 VCC
74282
G0 P1 G1 VCC P2 P0 G3 P3 S0 S1 P GND CYn+z G CYn CYn+y CYn+x CYnB CYnA G2
74283
SUM2 B2 A2 SUM1 A1 B1 CYI GND CYO SUM4 B4 A4 SUM3 A3 B3 VCC
74284
B2 B1 B0 A3 A0 A1 A2 GND Q7 Q6 Q5 Q4 EN2 EN1 B3 VCC
74285
B2 B1 B0 A3 A0 A1 A2 GND Q3 Q2 Q1 Q0 EN2 EN1 B3 VCC
74286
D6 D7 XMIT D8 PE PI/O GND D0 D1 D2 D3 D4 D5 VCC
74286
D7 D6 NC VCC D5 XMIT NC D6 NC PE PI/O GND NC D0 D1 D2 NC D3 NC D4


74287
74288
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74292
74293
74294
7429368
Connections:
A0-A19 address inputs
CAS0-CAS3 column address strobe
CASI column address strobe input
CS chip select input
LE latch enable input
MC0-MC3 mode control input
MSEL multiplexer select input
QE output enable input
Q0-Q9 address ouputs
RAS0-RAS3 row address strobe output
RASI row address strobe input
SEL0-SEL3 bank select input



74295

Pin	Signal	Pin	Signal
1	DS	14	VCC
2	D0	13	Q0
3	D1	12	Q1
4	D2	11	Q2
5	D3	10	Q3
6	SEL $\overline{S}$/L	9	CLK
7	GND	8	$\overline{ENO}$

742952

Pin	Signal	Pin	Signal
1	B7	24	VCC
2	B6	23	A7
3	B5	22	A6
4	B4	21	A5
5	B3	20	A4
6	B2	19	A3
7	B1	18	A2
6	B0	17	A1
9	$\overline{EN}$ B	16	A0
10	CLK B	J5	$\overline{EN}$ A
11	$\overline{CE}$ B	14	CLK A
12	GND	13	$\overline{CE}$ A

7429520

Pin	Signal	Pin	Signal
1	I0	24	VCC
2	I1	23	S0
3	D0	22	S1
4	D1	21	Q0
5	D2	20	Q1
6	D3	19	Q2
7	D4	18	Q3
8	D5	17	Q4
9	D6	16	Q5
10	D7	15	Q6
11	CLK	14	Q7
12	GND	13	$\overline{ENO}$

7429521

Pin	Signal	Pin	Signal
1	I0	24	VCC
2	I1	23	S0
3	D0	22	S1
4	D1	21	Q0
5	D2	20	Q1
6	D3	19	Q2
7	D4	18	Q3
8	D5	17	Q4
9	D6	16	Q5
10	D7	15	Q6
11	CLK	14	Q7
12	GND	13	$\overline{ENO}$

742953

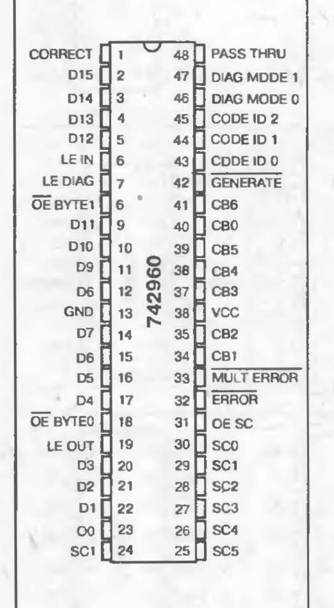
Pin	Signal	Pin	Signal
1	B7	24	VCC
2	B6	23	A7
3	B5	22	A6
4	B4	21	A5
5	B3	20	A4
6	B2	19	A3
7	B1	18	A2
8	B0	17	A1
9	$\overline{EN}$ B	16	A0
10	CLK B	15	$\overline{EN}$ A
11	$\overline{CE}$ B	14	CLK A
12	GND	13	$\overline{CE}$ A

742961

Pin	Signal	Pin	Signal
1	S	24	VCC
2	OEY	23	$\overline{OED}$
3	$\overline{DO0}$	22	$\overline{DO3}$
4	$\overline{B0}$	21	$\overline{B3}$
5	Y0	20	Y3
6	$\overline{DI0}$	19	$\overline{DI3}$
7	$\overline{DI1}$	18	$\overline{DI2}$
6	Y1	17	Y2
9	$\overline{B1}$	16	$\overline{B2}$
10	$\overline{DO1}$	15	$\overline{DO2}$
11	LEY	14	$\overline{OEB}$
12	GND	13	LEB

Connections:

B0-B3	bidirectional system data bus
OEB	output enable for B
LEB	latch enable for B
Y0-Y3	bidirectional EDC data bus
LEY	latch enable for Y
OEY	output enable for Y
S	select input for input data multiplexer
DO0-DO3	data outputs to memory data inputs
OED	output enable for DO
DI0-DI3	data inputs from memory



742962

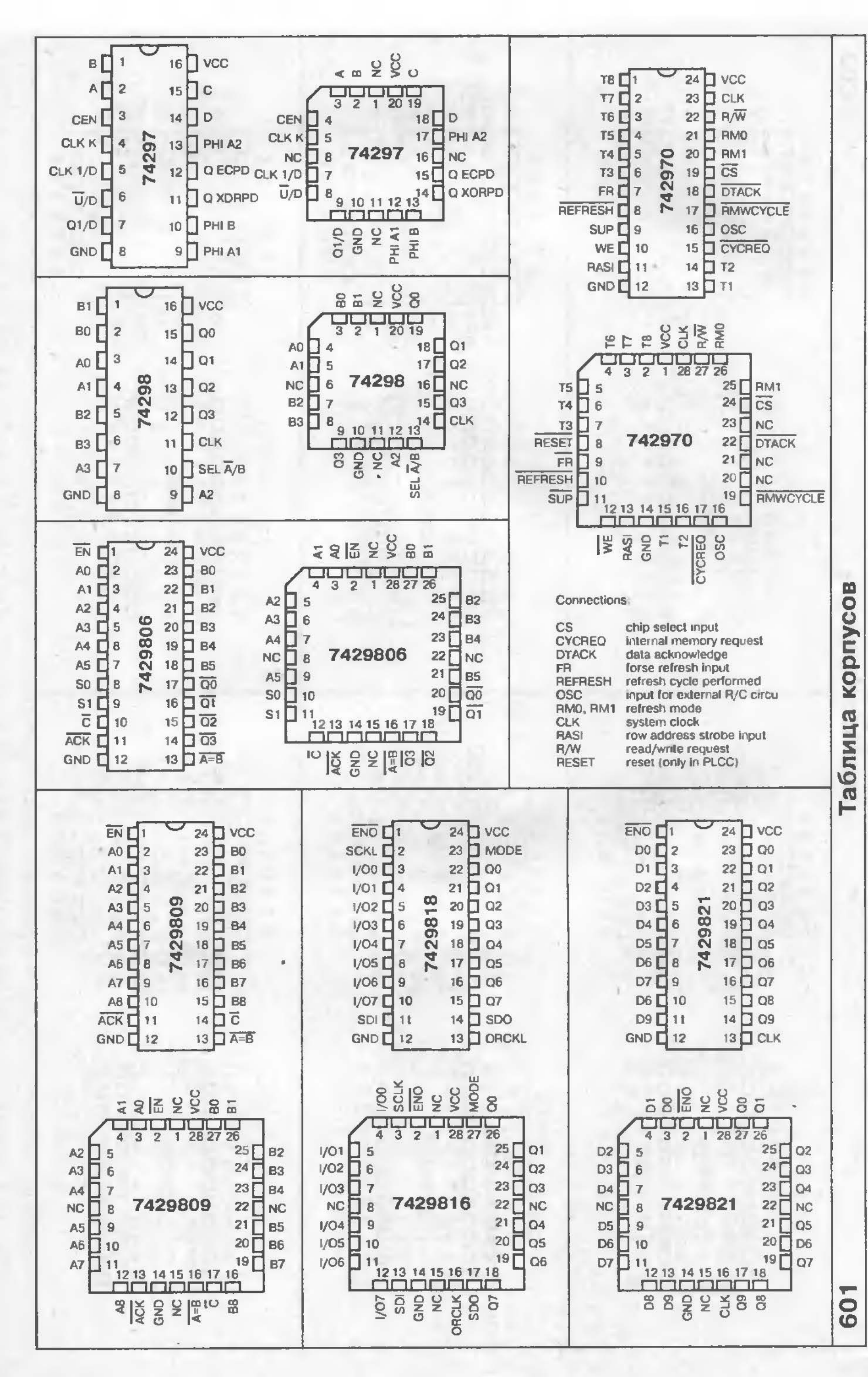
Pin	Signal	Pin	Signal
1	S	24	VCC
2	$\overline{DEY}$	23	$\overline{DED}$
3	$\overline{DO0}$	22	$\overline{DO3}$
4	B0	21	B3
5	$\overline{Y0}$	20	$\overline{Y3}$
6	$\overline{DI0}$	19	$\overline{DI3}$
7	$\overline{DI1}$	16	$\overline{DI2}$
6	$\overline{Y1}$	17	Y2
9	B1	16	B2
10	$\overline{DD1}$	15	$\overline{DO2}$
11	LEY	14	$\overline{DEB}$
12	GND	13	LEB

Connections:

B0-B3	bidirectional system data bus
OEB	output enable for B
LEB	latch enable for B
Y0-Y3	bidirectional EDC data bus
LEY	latch enable for Y
OEY	output enable for Y
S	select input for Input data multiplexer
DO0-DO3	data outputs to memory data inputs
OED	output enable for DO
DI0-DI3	data inputs from memory

742968

Pin	Signal	Pin	Signal
1	$\overline{CS}$	48	$\overline{CAS1}$
2	MSEL	47	$\overline{RAS0}$
3	AR0	46	$\overline{CAS0}$
4	AC0	45	$\overline{RAS1}$
5	AR1	44	$\overline{CAS1}$
6	AC1	43	O0
7	AR2	42	O1
8	AC2	41	Q2
9	AR3	40	Q3
10	AC3	39	Q4
11	AR4	38	GND
12	AC4	37	$\overline{OE}$
13	GND	38	VCC
14	LE	35	Q5
15	AR5	34	Q6
16	AC5	33	Q7
17	AR6	32	Q8
16	AC6	31	$\overline{RAS2}$
19	AR7	30	$\overline{CAS2}$
20	AC7	29	$\overline{RAS3}$
21	AR8	28	$\overline{CAS3}$
22	AC8	27	$\overline{RASI}$
23	SEL0	26	MC01
24	SEL1	25	MC1


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7429821
Connections:
CS chip select input
CYCREQ internal memory request
DTACK data acknowledge
FR forse refresh input
REFRESH refresh cycle performed
OSC input for external R/C circu
RM0, RM1 refresh mode
CLK system clock
RASI row address strobe input
R/W read/write request
RESET reset (only in PLCC)

7429822

Pin	DIP-24	PLCC-28
1	$\overline{ENO}$	NC
2	$\overline{D0}$	$\overline{ENO}$
3	$\overline{D1}$	$\overline{D0}$
4	$\overline{D2}$	$\overline{D1}$
5	$\overline{D3}$	$\overline{D2}$
6	$\overline{D4}$	$\overline{D3}$
7	$\overline{D5}$	$\overline{D4}$
8	$\overline{D6}$	NC
9	$\overline{D7}$	$\overline{D5}$
10	$\overline{D8}$	$\overline{D6}$
11	$\overline{D9}$	$\overline{D7}$
12	GND	$\overline{D8}$
13	CLK	$\overline{D9}$
14	Q9	GND
15	Q8	NC
16	Q7	CLK
17	Q6	Q9
18	Q5	Q8
19	Q4	Q7
20	Q3	Q6
21	Q2	Q5
22	Q1	NC
23	Q0	Q4
24	VCC	Q3
25		Q2
26		VCC
27		Q0
28		Q1

7429823

Pin	DIP-24	PLCC-28
1	$\overline{ENO}$	NC
2	D0	$\overline{ENO}$
3	D1	D0
4	D2	D1
5	D3	D2
6	D4	D3
7	D5	D4
8	D6	NC
9	D7	D5
10	D8	D6
11	D9	D7
12	GND	D8
13	CLK	$\overline{CLR}$
14	$\overline{CLKEN}$	GND
15	Q8	NC
16	Q7	CLK
17	Q6	$\overline{CLKEN}$
18	Q5	Q8
19	Q4	Q7
20	Q3	Q6
21	Q2	Q5
22	Q1	NC
23	Q0	Q4
24	VCC	Q3
25		Q2
26		Q1
27		Q0
28		VCC

7429824

Pin	DIP-24	PLCC-28
1	$\overline{ENO}$	NC
2	$\overline{D0}$	$\overline{ENO}$
3	$\overline{D1}$	$\overline{D0}$
4	$\overline{D2}$	$\overline{D1}$
5	$\overline{D3}$	$\overline{D2}$
6	$\overline{D4}$	$\overline{D3}$
7	$\overline{D5}$	$\overline{D4}$
8	$\overline{D6}$	NC
9	$\overline{D7}$	$\overline{D5}$
10	$\overline{D8}$	$\overline{D6}$
11	$\overline{CLR}$	$\overline{D7}$
12	GND	$\overline{D8}$
13	CLK	$\overline{CLR}$
14	$\overline{CLKEN}$	GND
15	Q8	NC
16	Q7	CLK
17	Q6	$\overline{CLKEN}$
18	Q5	Q8
19	Q4	Q7
20	Q3	Q6
21	Q2	Q5
22	Q1	NC
23	Q0	Q4
24	VCC	Q3
25		Q2
26		Q1
27		Q0
28		VCC

7429825

Pin	DIP-24	PLCC-28
1	$\overline{END1}$	NC
2	$\overline{END2}$	$\overline{ENO1}$
3	D0	$\overline{ENO2}$
4	D1	D0
5	D2	D1
6	D3	D2
7	D4	D3
8	D5	NC
9	D6	D4
10	D7	D5
11	$\overline{CLR}$	D6
12	GND	D7
13	CLK	$\overline{CLR}$
14	$\overline{CLKEN}$	GND
15	Q7	NC
16	Q6	CLK
17	Q5	$\overline{CLKEN}$
18	Q4	Q7
19	Q3	Q6
20	Q2	Q5
21	Q1	Q4
22	Q0	NC
23	$\overline{ENO3}$	Q3
24	VCC	Q2
25		Q1
26		Q0
27		$\overline{END3}$
28		VCC

7429826

Pin	DIP-24	PLCC-28
1	$\overline{END1}$	NC
2	$\overline{ENO2}$	$\overline{ENO1}$
3	$\overline{D0}$	$\overline{ENO2}$
4	$\overline{D1}$	$\overline{D0}$
5	$\overline{D2}$	$\overline{D1}$
6	$\overline{D3}$	$\overline{D2}$
7	$\overline{D4}$	$\overline{D3}$
8	$\overline{D5}$	NC
9	$\overline{D6}$	$\overline{D4}$
10	$\overline{D7}$	$\overline{D5}$
11	$\overline{CLR}$	$\overline{D6}$
12	GND	$\overline{D7}$
13	CLK	$\overline{CLR}$
14	$\overline{CLKEN}$	GND
15	Q7	NC
16	Q6	CLK
17	Q5	$\overline{CLKEN}$
18	Q4	Q7
19	Q3	Q6
20	Q2	Q5
21	Q1	Q4
22	Q0	NC
23	$\overline{ENO3}$	Q3
24	VCC	Q2
25		Q1
26		Q0
27		$\overline{ENO3}$
28		VCC

7429827

Pin	DIP-24	PLCC-28
1	$\overline{ENO}$	NC
2	D0	$\overline{ENO}$
3	D1	D0
4	D2	D1
5	D3	D2
6	D4	D3
7	D5	D4
8	D6	NC
9	D7	D5
10	D8	D6
11	D9	D7
12	GND	D8
13	$\overline{EN1}$	D9
14	Q9	GND
15	Q8	NC
16	Q7	EN1
17	Q6	Q9
18	Q5	Q8
19	Q4	Q7
20	Q3	Q6
21	Q2	Q5
22	Q1	NC
23	Q0	Q4
24	VCC	Q3
25		Q2
26		Q1
27		Q0
28		VCC

7429828

Pin	Signal	Pin	Signal
1	$\overline{EN0}$	24	VCC
2	D0	23	$\overline{Q0}$
3	D1	22	$\overline{Q1}$
4	D2	21	$\overline{Q2}$
5	D3	20	$\overline{Q3}$
6	D4	19	$\overline{Q4}$
7	D5	18	$\overline{Q5}$
8	D6	17	$\overline{Q6}$
9	D7	16	$\overline{Q7}$
10	D8	15	$\overline{Q8}$
11	D9	14	$\overline{Q9}$
12	GND	13	$\overline{EN1}$

7429828 (PLCC)

Pin	Signal	Pin	Signal
1	NC	15	NC
2	$\overline{EN0}$	16	$\overline{EN1}$
3	D0	17	$\overline{Q9}$
4	D1	18	$\overline{Q8}$
5	D2	19	$\overline{Q7}$
6	D3	20	$\overline{Q6}$
7	D4	21	$\overline{Q5}$
8	NC	22	NC
9	D5	23	$\overline{Q4}$
10	D6	24	$\overline{Q3}$
11	D7	25	$\overline{Q2}$
12	D8	26	$\overline{Q1}$
13	D9	27	$\overline{Q0}$
14	GND	28	VCC

7429833

Pin	Signal	Pin	Signal
1	$\overline{ENBA}$	24	VCC
2	A0	23	B0
3	A1	22	B1
4	A2	21	B2
5	A3	20	B3
6	A4	19	B4
7	A5	18	B5
8	A6	17	B6
9	A7	16	B7
10	$\overline{ERR}$	15	P
11	$\overline{CLR}$	14	$\overline{ENBA}$
12	GND	13	CLK

7429833 (PLCC)

Pin	Signal	Pin	Signal
1	NC	15	NC
2	$\overline{ENBA}$	16	CLK
3	A0	17	$\overline{ENBA}$
4	A1	18	P
5	A2	19	B7
6	A3	20	B6
7	A4	21	B5
8	NC	22	NC
9	A5	23	B4
10	A6	24	B3
11	A7	25	B2
12	$\overline{ERR}$	26	B1
13	$\overline{CLR}$	27	B0
14	GND	28	VCC

7429834

Pin	Signal	Pin	Signal
1	$\overline{ENBA}$	24	VCC
2	A0	23	B0
3	A1	22	B1
4	A2	21	B2
5	A3	20	B3
6	A4	19	B4
7	A5	18	B5
8	A6	17	B6
9	A7	16	B7
10	$\overline{ERR}$	15	P
11	$\overline{CLR}$	14	$\overline{ENBA}$
12	GND	13	CLK

7429834 (PLCC)

Pin	Signal	Pin	Signal
1	NC	15	NC
2	$\overline{ENBA}$	16	CLK
3	A0	17	$\overline{ENBA}$
4	A1	18	P
5	A2	19	B7
6	A3	20	B6
7	A4	21	B5
8	NC	22	NC
9	A5	23	B4
10	A6	24	B3
11	A7	25	B2
12	$\overline{ERR}$	26	B1
13	$\overline{CLR}$	27	B0
14	GND	28	VCC

7429841

Pin	Signal	Pin	Signal
1	$\overline{EN0}$	24	VCC
2	D0	23	Q0
3	D1	22	Q1
4	D2	21	Q2
5	D3	20	Q3
6	D4	19	Q4
7	D5	18	Q5
8	D6	17	Q6
9	D7	16	Q7
10	D8	15	Q8
11	D9	14	Q9
12	GND	13	ENL

7429841 (PLCC)

Pin	Signal	Pin	Signal
1	NC	15	NC
2	$\overline{EN0}$	16	ENL
3	D0	17	Q9
4	D1	18	Q8
5	D2	19	Q7
6	D3	20	Q6
7	D4	21	Q5
8	NC	22	NC
9	D5	23	Q4
10	D6	24	Q3
11	D7	25	Q2
12	D8	26	Q1
13	D9	27	Q0
14	GND	28	VCC

7429842

Pin	Signal	Pin	Signal
1	$\overline{EN0}$	24	VCC
2	$\overline{D0}$	23	Q0
3	$\overline{D1}$	22	Q1
4	$\overline{D2}$	21	Q2
5	$\overline{D3}$	20	Q3
6	$\overline{D4}$	19	Q4
7	$\overline{D5}$	18	Q5
8	$\overline{D6}$	17	Q6
9	$\overline{D7}$	16	Q7
10	$\overline{D8}$	15	Q8
11	$\overline{D9}$	14	Q9
12	GND	13	ENL

7429842 (PLCC)

Pin	Signal	Pin	Signal
1	NC	15	NC
2	$\overline{EN0}$	16	ENL
3	$\overline{D0}$	17	Q9
4	$\overline{D1}$	18	Q8
5	$\overline{D2}$	19	Q7
6	$\overline{D3}$	20	Q6
7	$\overline{D4}$	21	Q5
8	NC	22	NC
9	$\overline{D5}$	23	Q4
10	$\overline{D6}$	24	Q3
11	$\overline{D7}$	25	Q2
12	$\overline{D8}$	26	Q1
13	$\overline{D9}$	27	Q0
14	GND	28	VCC

7429843

Pin	Signal	Pin	Signal
1	$\overline{EN0}$	24	VCC
2	D0	23	Q0
3	D1	22	Q1
4	D2	21	Q2
5	D3	20	Q3
6	D4	19	Q4
7	D5	18	Q5
8	D6	17	Q6
9	D7	16	Q7
10	D8	15	Q8
11	$\overline{CLR}$	14	$\overline{S}$
12	GND	13	ENL

7429843 (PLCC)

Pin	Signal	Pin	Signal
1	NC	15	NC
2	$\overline{EN0}$	16	ENL
3	D0	17	$\overline{S}$
4	D1	18	Q8
5	D2	19	Q7
6	D3	20	Q6
7	D4	21	Q5
8	NC	22	NC
9	D5	23	Q4
10	D6	24	Q3
11	D7	25	Q2
12	D8	26	Q1
13	$\overline{CLR}$	27	Q0
14	GND	28	VCC

7429844 (DIP-24)

Pin	Signal	Pin	Signal
1	$\overline{ENO}$	24	VCC
2	$\overline{D0}$	23	Q0
3	$\overline{D1}$	22	Q1
4	$\overline{D2}$	21	Q2
5	$\overline{D3}$	20	Q3
6	$\overline{D4}$	19	Q4
7	$\overline{D5}$	18	Q5
8	$\overline{D6}$	17	Q6
9	$\overline{D7}$	16	Q7
10	$\overline{D8}$	15	Q6
11	$\overline{CLR}$	14	$\overline{S}$
12	GND	13	ENL

7429844 (PLCC-28)

Pin	Signal	Pin	Signal	Pin	Signal	Pin	Signal
1	NC	8	NC	15	NC	22	NC
2	$\overline{ENO}$	9	$\overline{D5}$	16	ENL	23	Q4
3	$\overline{D0}$	10	$\overline{Q6}$	17	$\overline{S}$	24	Q3
4	$\overline{D1}$	11	$\overline{D7}$	18	Q8	25	Q2
5	$\overline{D2}$	12	$\overline{D8}$	19	Q7	26	Q1
6	$\overline{D3}$	13	$\overline{CLR}$	20	Q6	27	Q0
7	$\overline{D4}$	14	GND	21	Q5	28	VCC

7429845 (DIP-24)

Pin	Signal	Pin	Signal
1	$\overline{ENO1}$	24	VCC
2	$\overline{ENO2}$	23	$\overline{ENO3}$
3	D0	22	Q0
4	D1	21	Q1
5	D2	20	Q2
6	D3	19	Q3
7	D4	18	Q4
8	D5	17	Q5
9	D6	16	Q6
10	D7	15	Q7
11	$\overline{CLR}$	14	$\overline{S}$
12	GND	13	ENL

7429845 (PLCC-28)

Pin	Signal	Pin	Signal	Pin	Signal	Pin	Signal
1	NC	8	NC	15	NC	22	NC
2	$\overline{ENO1}$	9	D4	16	ENL	23	Q3
3	$\overline{ENO2}$	10	D5	17	$\overline{S}$	24	Q2
4	D0	11	D8	18	Q7	25	Q1
5	D1	12	D7	19	Q8	26	Q0
8	D2	13	$\overline{CLR}$	20	Q5	27	$\overline{ENO3}$
7	D3	14	GND	21	Q4	28	VCC

7429846 (DIP-24)

Pin	Signal	Pin	Signal
1	$\overline{ENO1}$	24	VCC
2	$\overline{ENO2}$	23	$\overline{ENO3}$
3	$\overline{D0}$	22	Q0
4	$\overline{D1}$	21	Q1
5	$\overline{D2}$	20	Q2
6	$\overline{D3}$	19	Q3
7	$\overline{D4}$	18	Q4
8	$\overline{D5}$	17	Q5
9	$\overline{D6}$	16	Q6
10	$\overline{D7}$	15	Q7
11	$\overline{CLR}$	14	$\overline{S}$
12	GND	13	ENL

7429846 (PLCC-28)

Pin	Signal	Pin	Signal	Pin	Signal	Pin	Signal
1	NC	8	NC	15	NC	22	NC
2	$\overline{ENO1}$	9	$\overline{D4}$	16	ENL	23	Q3
3	$\overline{ENO2}$	10	$\overline{D5}$	17	$\overline{S}$	24	Q2
4	$\overline{D0}$	11	$\overline{D8}$	18	Q7	25	Q1
5	$\overline{D1}$	12	$\overline{D7}$	19	Q6	26	Q0
6	$\overline{D2}$	13	$\overline{CLR}$	20	Q5	27	$\overline{ENO3}$
7	$\overline{D3}$	14	GND	21	Q4	28	VCC

7429853 (DIP-24)

Pin	Signal	Pin	Signal
1	$\overline{ENBA}$	24	VCC
2	A0	23	B0
3	A1	22	B1
4	A2	21	B2
5	A3	20	B3
6	A4	19	B4
7	A5	18	B5
8	A6	17	B8
9	A7	16	B7
10	$\overline{ERR}$	15	P
11	$\overline{CLR}$	14	$\overline{ENBA}$
12	GND	13	$\overline{ENL}$

7429853 (PLCC-28)

Pin	Signal	Pin	Signal	Pin	Signal	Pin	Signal
1	NC	8	NC	15	NC	22	NC
2	$\overline{ENBA}$	9	A5	16	$\overline{ENL}$	23	B4
3	A0	10	A6	17	$\overline{ENBA}$	24	B3
4	A1	11	A7	18	P	25	B2
5	A2	12	$\overline{ERR}$	19	B7	26	B1
8	A3	13	$\overline{CLR}$	20	B6	27	B0
7	A4	14	GND	21	85	28	VCC

7429854 (DIP-24)

Pin	Signal	Pin	Signal
1	$\overline{ENBA}$	24	VCC
2	A0	23	B0
3	A1	22	B1
4	A2	21	B2
5	A3	20	B3
6	A4	19	B4
7	A5	18	B5
8	A6	17	B8
9	A7	16	B7
10	$\overline{ERR}$	15	P
11	$\overline{CLR}$	14	$\overline{ENBA}$
12	GND	13	$\overline{ENL}$

7429854 (PLCC-28)

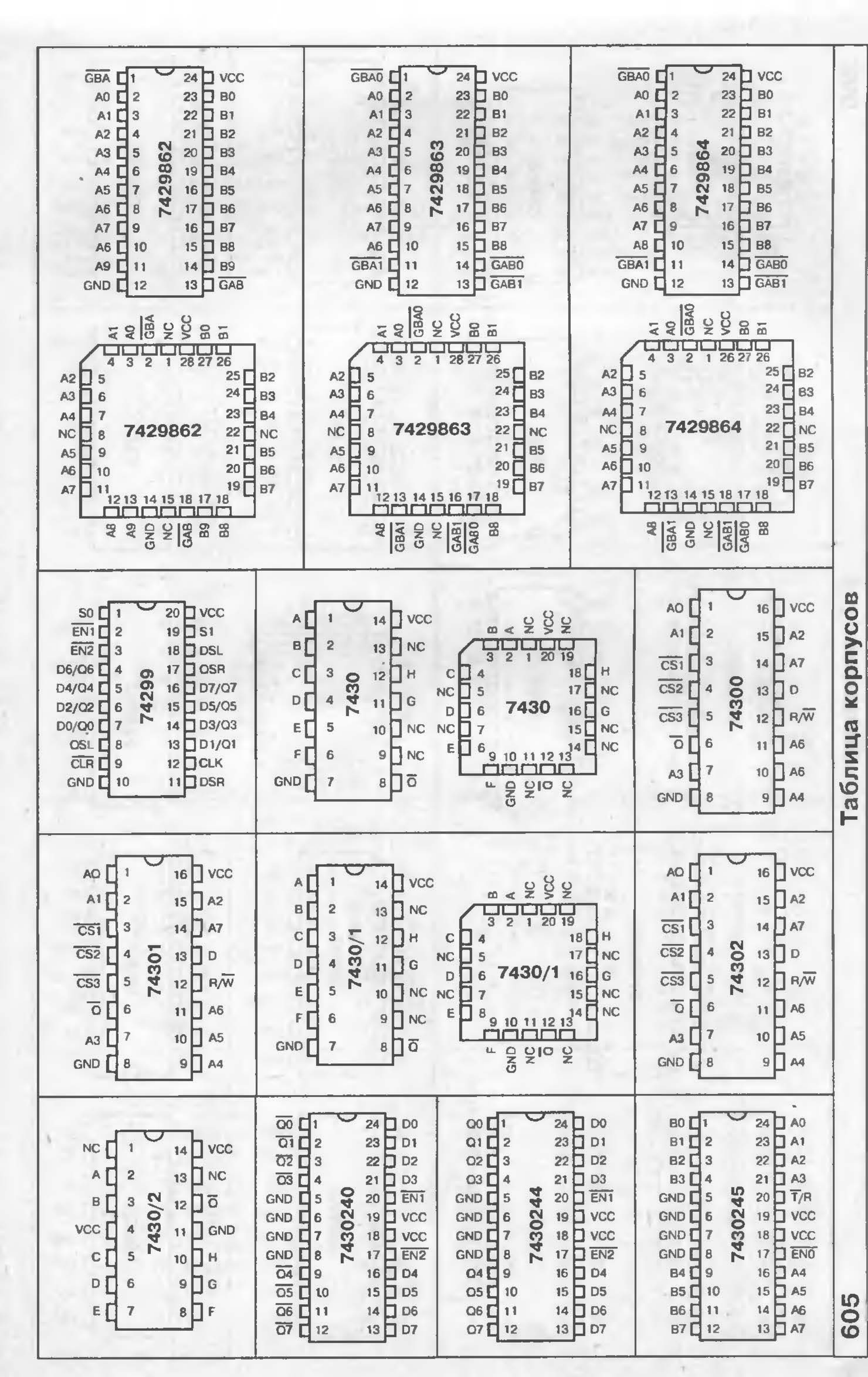
Pin	Signal	Pin	Signal	Pin	Signal	Pin	Signal
1	NC	8	NC	15	NC	22	NC
2	$\overline{ENBA}$	9	A5	16	$\overline{ENL}$	23	B4
3	A0	10	A6	17	$\overline{ENBA}$	24	B3
4	A1	11	A7	18	P	25	B2
5	A2	12	$\overline{ERR}$	19	B7	26	B1
8	A3	13	$\overline{CLR}$	20	B6	27	B0
7	A4	14	GND	21	B5	28	VCC

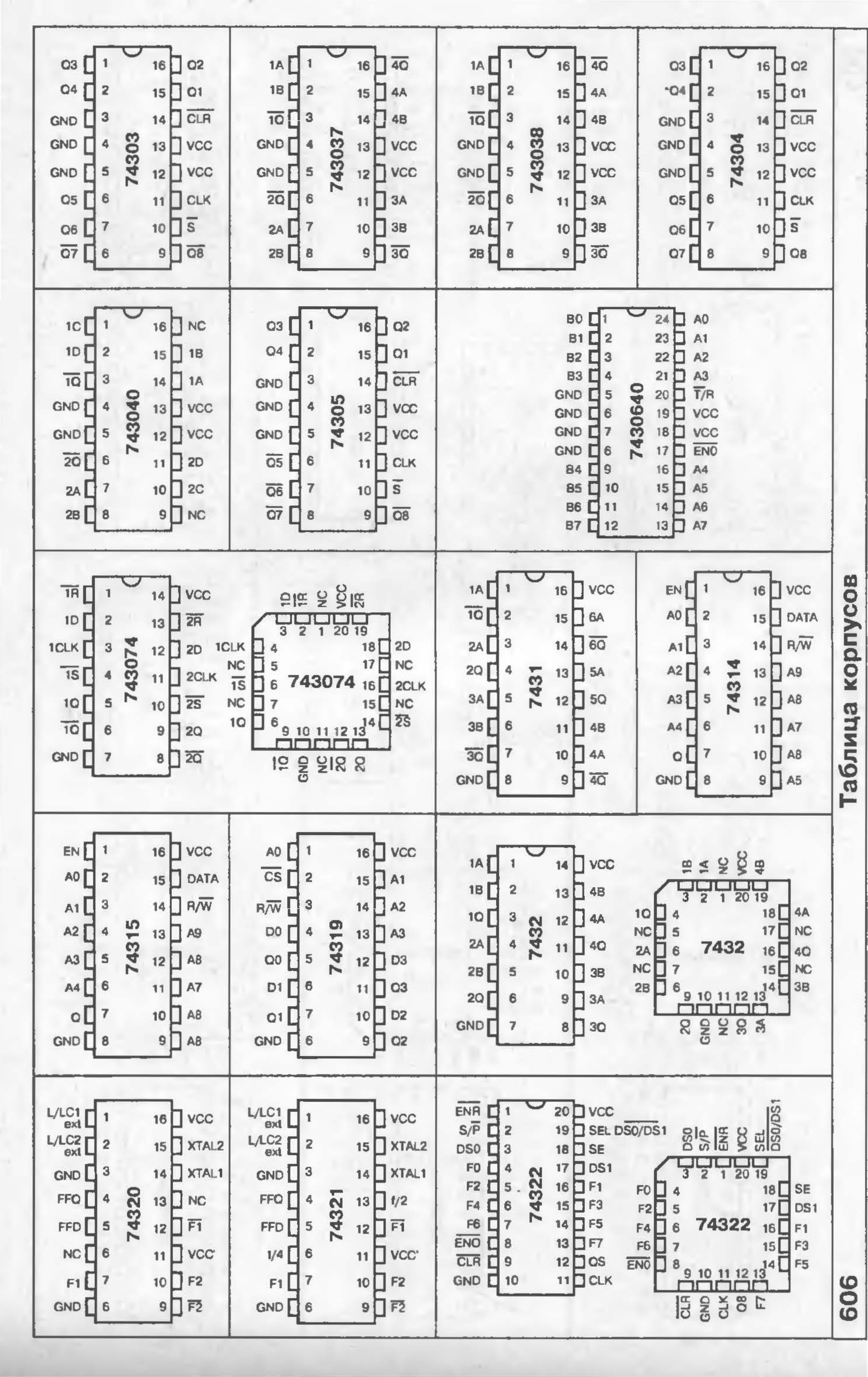
7429861 (DIP-24)

Pin	Signal	Pin	Signal
1	$\overline{GBA}$	24	VCC
2	A0	23	B0
3	A1	22	B1
4	A2	21	B2
5	A3	20	B3
6	A4	19	B4
7	A5	18	B5
8	A6	17	B6
9	A7	18	B7
10	A8	15	B8
11	A9	14	B9
12	GND	13	$\overline{GAB}$

7429881 (PLCC-28)

Pin	Signal	Pin	Signal	Pin	Signal	Pin	Signal
1	NC	8	NC	15	NC	22	NC
2	$\overline{GBA}$	9	A5	16	$\overline{GAB}$	23	B4
3	A0	10	A6	17	B9	24	B3
4	A1	11	A7	18	B8	25	B2
5	A2	12	A8	19	87	26	B1
6	A3	13	A9	20	B6	27	B0
7	A4	14	GND	21	B5	28	VCC


7429862
7429863
7429864
7429862
7429863
7429864
74299
7430
7430
74300
74301
7430/1
7430/1
74302
7430/2
7430240
7430244
7430245


74303
Q3 1 16 Q2
Q4 2 15 Q1
GND 3 14 CLR
GND 4 13 VCC
GND 5 12 VCC
Q5 6 11 CLK
Q6 7 10 S
Q7 6 9 Q8
743037
1A 1 16 4Q
1B 2 15 4A
1Q 3 14 4B
GND 4 13 VCC
GND 5 12 VCC
2Q 6 11 3A
2A 7 10 3B
2B 8 9 3Q
743038
1A 1 16 4Q
1B 2 15 4A
1Q 3 14 4B
GND 4 13 VCC
GND 5 12 VCC
2Q 6 11 3A
2A 7 10 3B
2B 8 9 3Q
74304
Q3 1 16 Q2
Q4 2 15 Q1
GND 3 14 CLR
GND 4 13 VCC
GND 5 12 VCC
Q5 6 11 CLK
Q6 7 10 S
Q7 8 9 Q8
743040
1C 1 16 NC
1D 2 15 1B
1Q 3 14 1A
GND 4 13 VCC
GND 5 12 VCC
2Q 6 11 2D
2A 7 10 2C
2B 8 9 NC
74305
Q3 1 16 Q2
Q4 2 15 Q1
GND 3 14 CLR
GND 4 13 VCC
GND 5 12 VCC
Q5 6 11 CLK
Q6 7 10 S
Q7 8 9 Q8
7430640
B0 1 24 A0
B1 2 23 A1
B2 3 22 A2
B3 4 21 A3
GND 5 20 T/R
GND 6 19 VCC
GND 7 18 VCC
GND 6 17 ENO
B4 9 16 A4
B5 10 15 A5
B6 11 14 A6
B7 12 13 A7
743074
1R 1 14 VCC
1D 2 13 2R
1CLK 3 12 2D
1S 4 11 2CLK
1Q 5 10 2S
1Q 6 9 2Q
GND 7 8 2Q
743074
1D 1R NC VCC 2R
3 2 1 20 19
1CLK 4 18 2D
NC 5 17 NC
1S 6 16 2CLK
NC 7 15 NC
1Q 6 14 2S
9 10 11 12 13
1Q GND NC 2Q 2Q
7431
1A 1 16 VCC
1Q 2 15 6A
2A 3 14 6Q
2Q 4 13 5A
3A 5 12 5Q
3B 6 11 4B
3Q 7 10 4A
GND 8 9 4Q
74314
EN 1 16 VCC
A0 2 15 DATA
A1 3 14 R/W
A2 4 13 A9
A3 5 12 A8
A4 6 11 A7
Q 7 10 A8
GND 8 9 A5
74315
EN 1 16 VCC
A0 2 15 DATA
A1 3 14 R/W
A2 4 13 A9
A3 5 12 A8
A4 6 11 A7
Q 7 10 A8
GND 8 9 A8
74319
A0 1 16 VCC
CS 2 15 A1
R/W 3 14 A2
D0 4 13 A3
Q0 5 12 D3
D1 6 11 Q3
Q1 7 10 D2
GND 6 9 Q2
7432
1A 1 14 VCC
1B 2 13 4B
1Q 3 12 4A
2A 4 11 4Q
2B 5 10 3B
2Q 6 9 3A
GND 7 8 3Q
7432
1B 1A NC VCC 4B
3 2 1 20 19
1Q 4 18 4A
NC 5 17 NC
2A 6 16 4Q
NC 7 15 NC
2B 6 14 3B
9 10 11 12 13
2Q GND NC 3Q 3A
74320
L/LC1 ext 1 16 VCC
L/LC2 ext 2 15 XTAL2
GND 3 14 XTAL1
FFQ 4 13 NC
FFD 5 12 F1
NC 6 11 VCC
F1 7 10 F2
GND 6 9 F2
74321
L/LC1 ext 1 16 VCC
L/LC2 ext 2 15 XTAL2
GND 3 14 XTAL1
FFQ 4 13 f/2
FFD 5 12 F1
1/4 6 11 VCC'
F1 7 10 F2
GND 6 9 F2
74322
ENR 1 20 VCC
S/P 2 19 SEL DS0/DS1
DS0 3 18 SE
F0 4 17 DS1
F2 5 16 F1
F4 6 15 F3
F6 7 14 F5
ENO 8 13 F7
CLR 9 12 QS
GND 10 11 CLK
74322
DS0 S/P ENR VCC SEL DS0/DS1
3 2 1 20 19
F0 4 18 SE
F2 5 17 DS1
F4 6 16 F1
F6 7 15 F3
ENO 8 14 F5
9 10 11 12 13
CLR GND CLK Q8 F7

74323

Pin	Signal	Pin	Signal
1	S0	20	VCC
2	$\overline{EN1}$	19	S1
3	$\overline{EN2}$	18	DSL
4	D6/Q6	17	QSR
5	D4/Q4	16	D7/Q7
6	D2/Q2	15	D5/Q5
7	D0/Q0	14	D3/Q3
8	QSL	13	D1/Q1
9	$\overline{CLR}$	12	CLK
10	GND	11	DSR

74323 (PLCC)

Pin	Signal	Pin	Signal
3	$\overline{EN2}$	18	DSL
2	$\overline{EN1}$	17	QSR
1	S0	16	D7/Q7
20	VCC	15	D5/Q5
19	S1	14	D3/Q3
4	D6/Q6	9	$\overline{CLR}$
5	D4/Q4	10	GND
6	D2/Q2	11	DSR
7	D0/Q0	12	CLK
6	QSL	13	D1/Q1

74324

Pin	Signal	Pin	Signal
1	GND DSC	14	VCC OSC
2	BER	13	FC
3	Cext1	12	NC
4	Cext2	11	NC
5	$\overline{EN}$	10	NC
6	$\overline{Q}$	9	VCC
7	GND	8	Q

74325

Pin	Signal	Pin	Signal
1	GND	16	VCC
2	1Q	15	2Q
3	$\overline{1Q}$	14	$\overline{2Q}$
4	1Cext1	13	2Cext1
5	1Cext2	12	2Cext2
6	1FC	11	2FC
7	VCC OSC1	10	VCC DSC2
8	GND OSC1	9	GND OSC2

74326

Pin	Signal	Pin	Signal
1	GND	16	VCC
2	1Q	15	2Q
3	$\overline{1Q}$	14	$\overline{2Q}$
4	$\overline{1EN}$	13	$\overline{2EN}$
5	1Cext1	12	2Cext1
6	1Cext2	11	2Cext2
7	VCC OSC	10	2FC
8	GND DSC	9	1FC

74327

Pin	Signal	Pin	Signal
1	VCC OSC1	14	VCC
2	1FC	13	VCC DSC2
3	1Cext1	12	2FC
4	1Cext2	11	2Cext2
5	GND DSC1	10	2Cext1
6	$\overline{1Q}$	9	GND OSC2
7	GND	8	$\overline{2Q}$

7433

Pin	Signal	Pin	Signal
1	$\overline{1Q}$	14	VCC
2	1A	13	$\overline{4Q}$
3	1B	12	4A
4	$\overline{2Q}$	11	4B
5	2A	10	$\overline{3Q}$
6	2B	9	3A
7	GND	8	3B

7433 (PLCC)

Pin	Signal	Pin	Signal
3	1A	18	4A
2	$\overline{1Q}$	17	NC
1	NC	16	4B
20	VCC	15	NC
19	$\overline{4Q}$	14	$\overline{3Q}$
4	1B	9	2B
5	NC	10	GND
6	$\overline{2Q}$	11	NC
7	NC	12	3B
8	2A	13	3A

74330

Pin	Signal	Pin	Signal
1	E0	20	VCC
2	E1	19	E10
3	E2	18	E9
4	E3	17	E8
5	E4	16	E7
6	E5	15	E11/C
7	E8	14	Q5
8	Q0	13	Q4
9	Q1	12	Q3
10	GND	11	Q2

74331

Pin	Signal	Pin	Signal
1	E0	20	VCC
2	E1	19	E10
3	E2	18	E9
4	E3	17	E8
5	E4	16	E7
6	E5	15	E11/C
7	E6	14	Q5
8	Q0	13	Q4
9	Q1	12	Q3
10	GND	11	Q2

743374

Pin	Signal	Pin	Signal
1	Q0	20	D0
2	Q1	19	D1
3	Q2	18	D2
4	Q3	17	D3
5	GND	16	VCC
6	Q4	15	D4
7	Q5	14	D5
6	Q6	13	D6
9	Q7	12	D7
10	$\overline{EN0}$	11	CLK

7434

Pin	Signal	Pin	Signal
1	1A	14	VCC
2	1Q	13	6A
3	2A	12	6Q
4	2Q	11	5A
5	3A	10	6Q
6	3Q	9	4A
7	GND	8	4Q

7434 (PLCC)

Pin	Signal	Pin	Signal
3	1Q	18	6Q
2	1A	17	NC
1	NC	16	5A
20	VCC	15	NC
19	6A	14	5Q
4	2A	9	3Q
5	NC	10	GND
6	2Q	11	NC
7	NC	12	4Q
6	3A	13	4A

74340

Pin	Signal	Pin	Signal
1	$\overline{EN1}$	20	VCC
2	D0	19	$\overline{EN2}$
3	$\overline{Q7}$	18	$\overline{Q0}$
4	D1	17	D7
5	$\overline{Q6}$	16	$\overline{Q1}$
8	D2	15	D6
7	$\overline{Q5}$	14	$\overline{Q2}$
8	D3	13	D5
9	$\overline{Q4}$	12	$\overline{Q3}$
10	GND	11	D4

74341

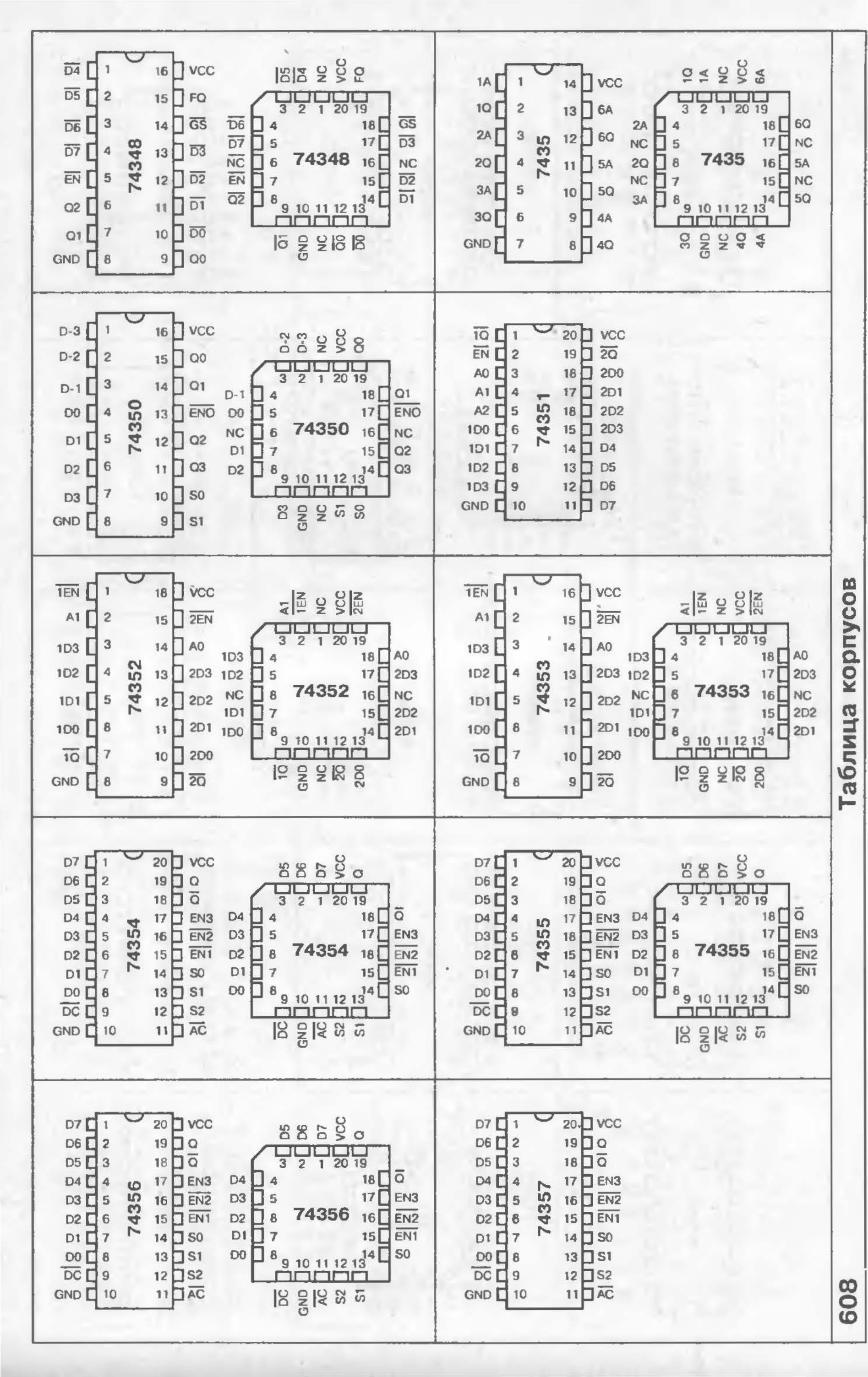
Pin	Signal	Pin	Signal
1	$\overline{EN1}$	20	VCC
2	D0	19	EN2
3	Q7	18	Q0
4	D1	17	D7
5	Q6	16	Q1
6	D2	15	D6
7	Q5	14	Q2
6	D3	13	D5
9	Q4	12	Q3
10	GND	11	D4

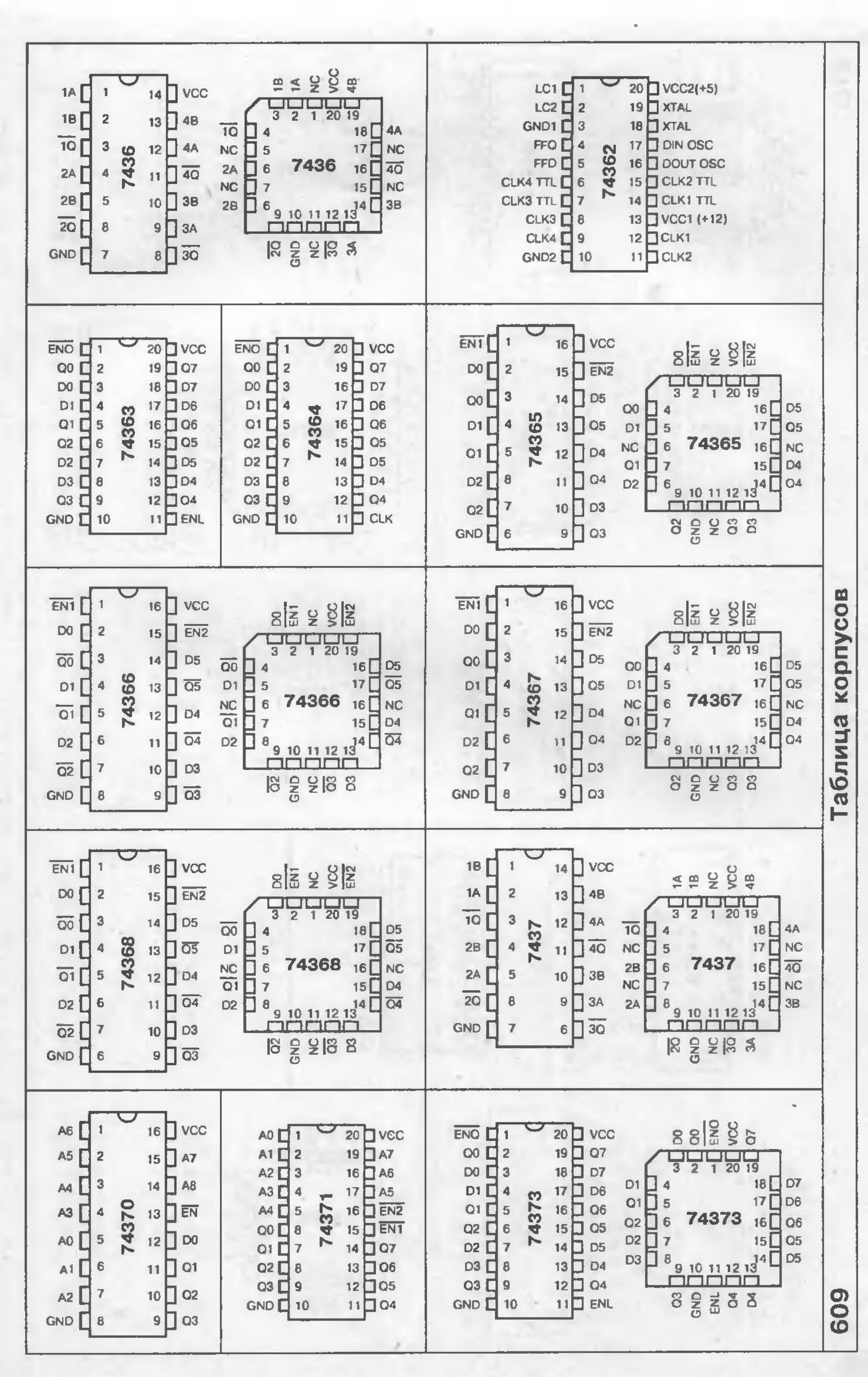
74344

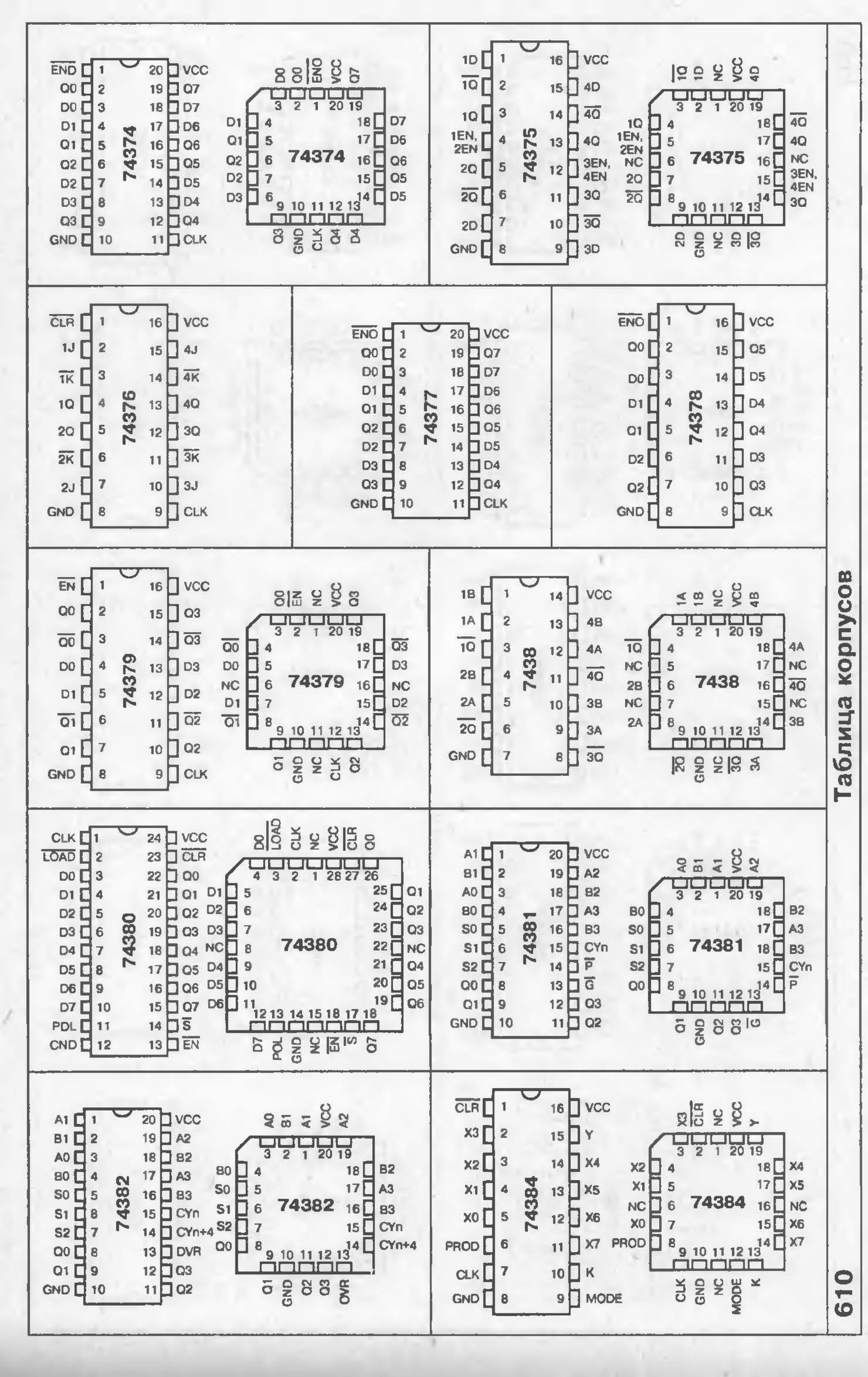
Pin	Signal	Pin	Signal
1	$\overline{EN1}$	20	VCC
2	D0	19	$\overline{EN2}$
3	Q7	16	Q0
4	D1	17	D7
5	Q6	16	Q1
6	D2	15	D6
7	Q5	14	Q2
6	D3	13	D5
9	Q4	12	Q3
10	GND	11	D4

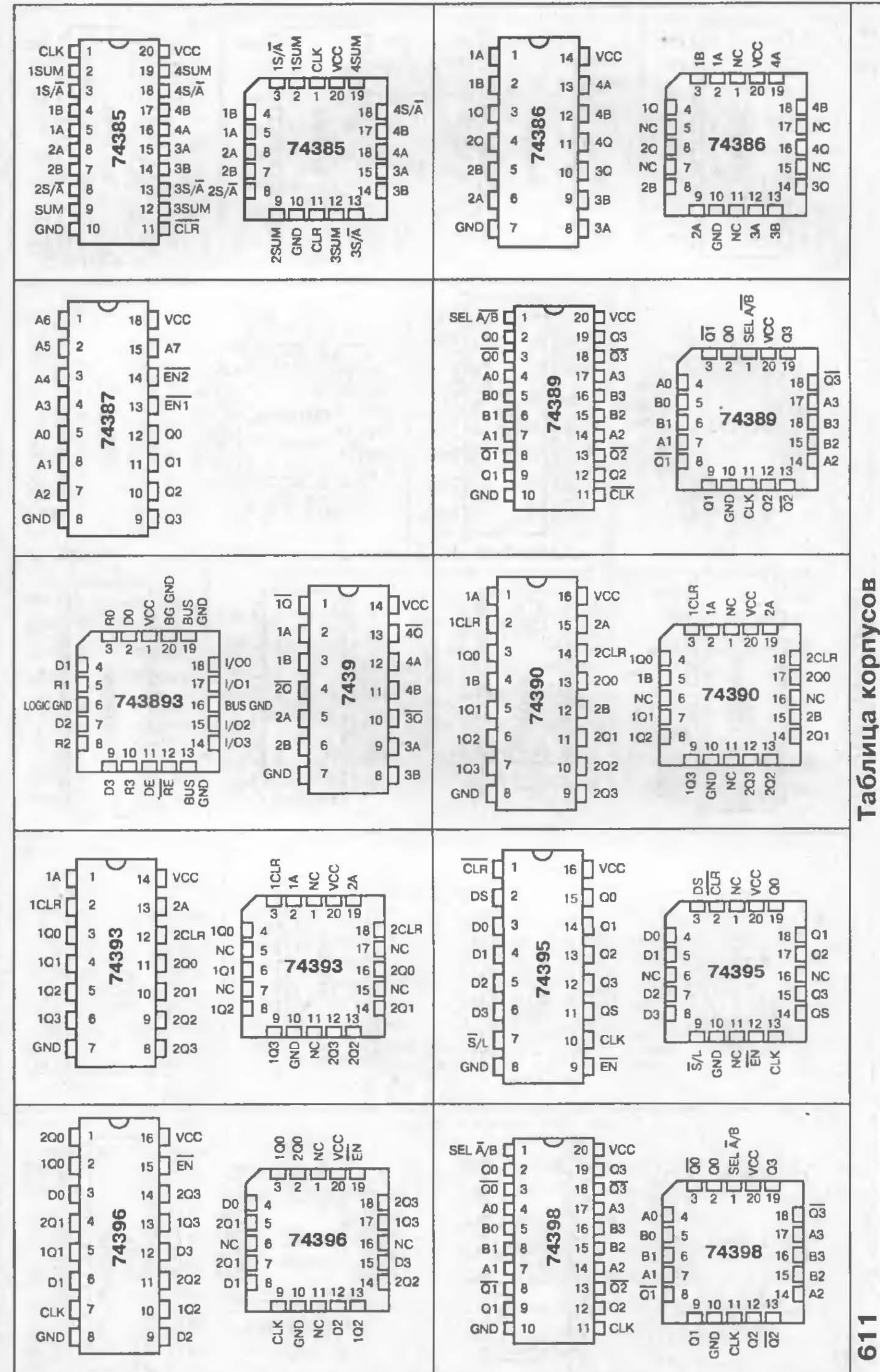
74347

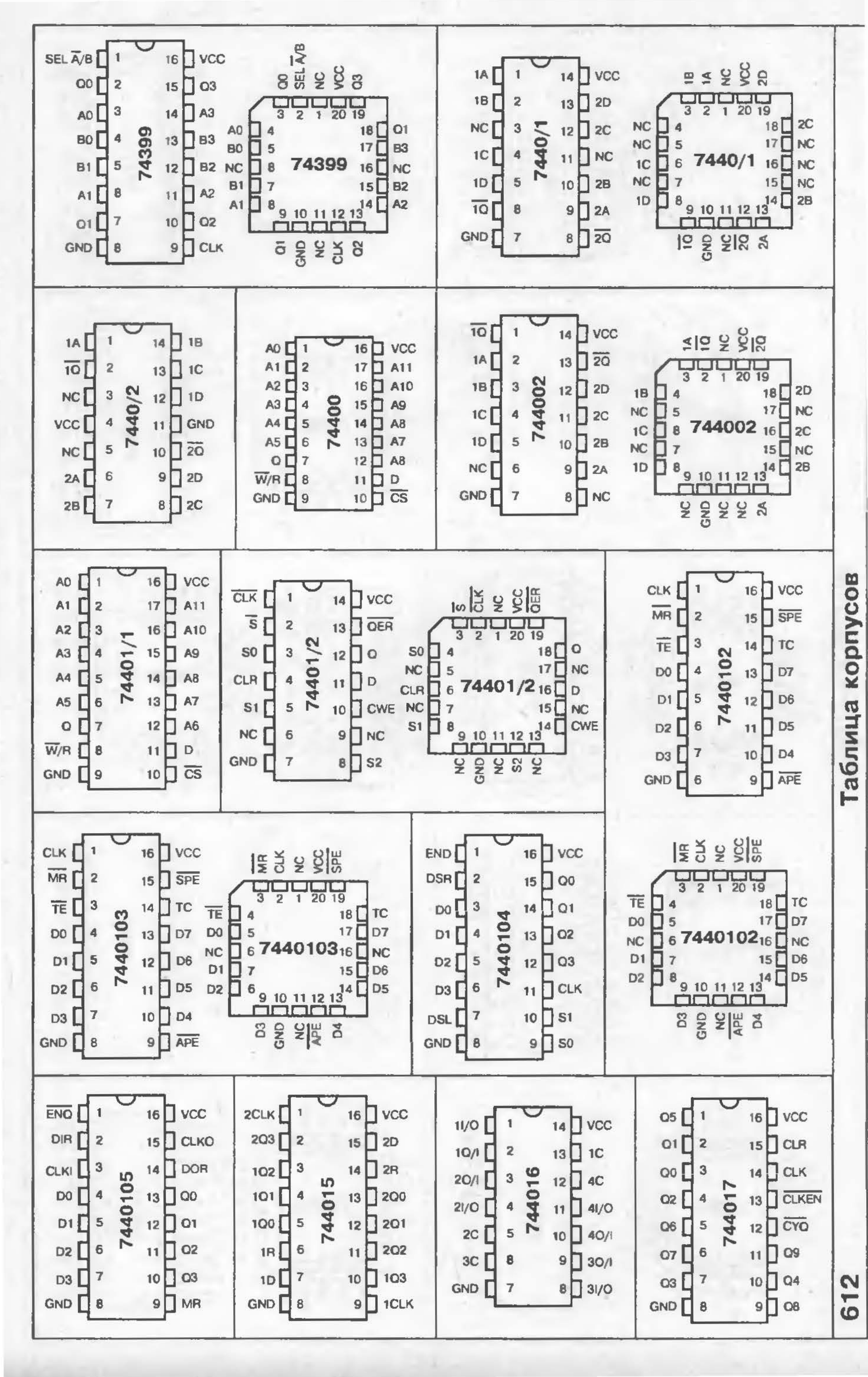
Pin	Signal	Pin	Signal
1	D1	16	VCC
2	D2	15	f
3	$\overline{LT}$	14	g
4	$\overline{BI/RBO}$	13	a
5	$\overline{RBI}$	12	b
6	D3	11	c
7	D0	10	d
6	GND	9	e

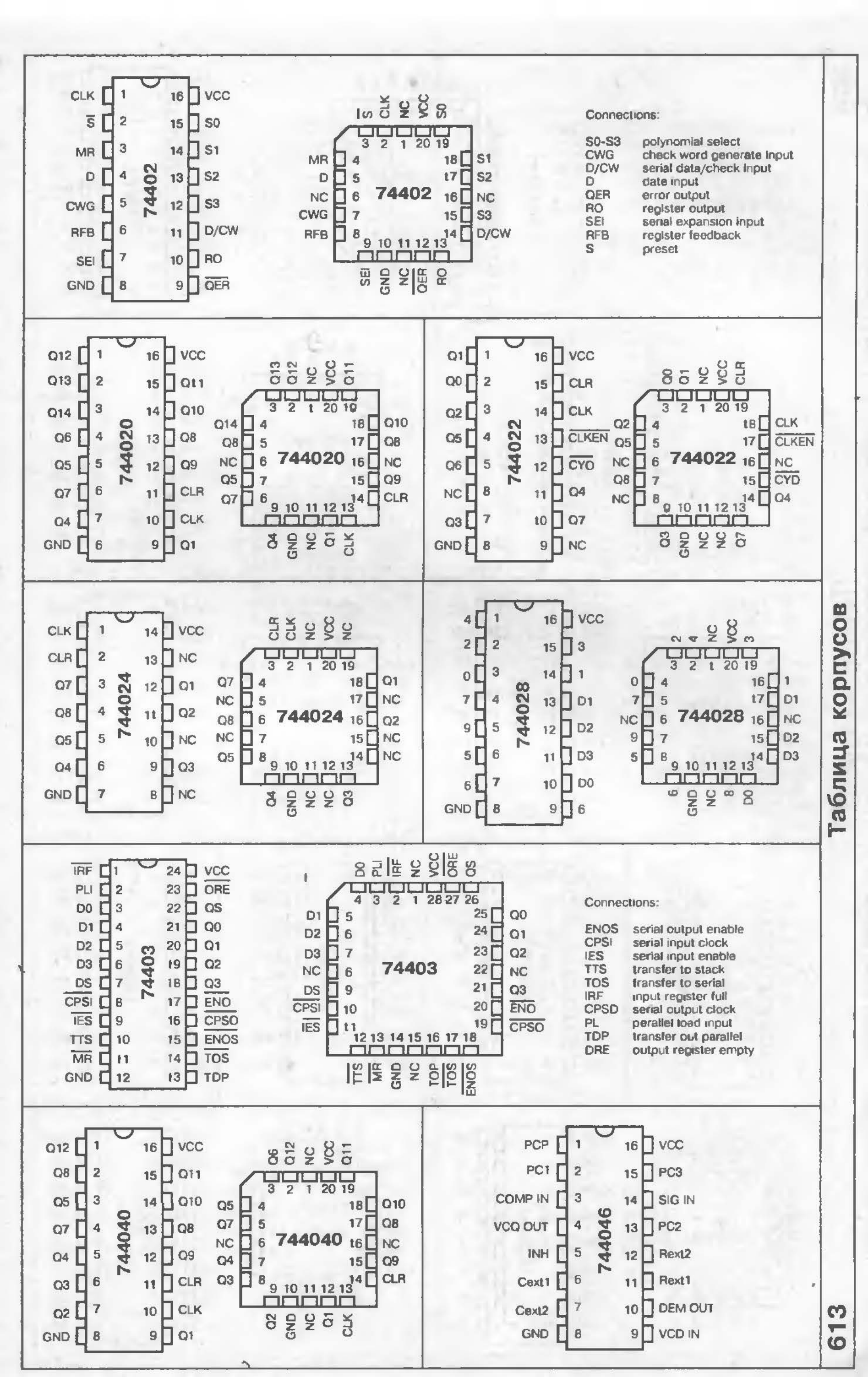

74348
74348
7435
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74357

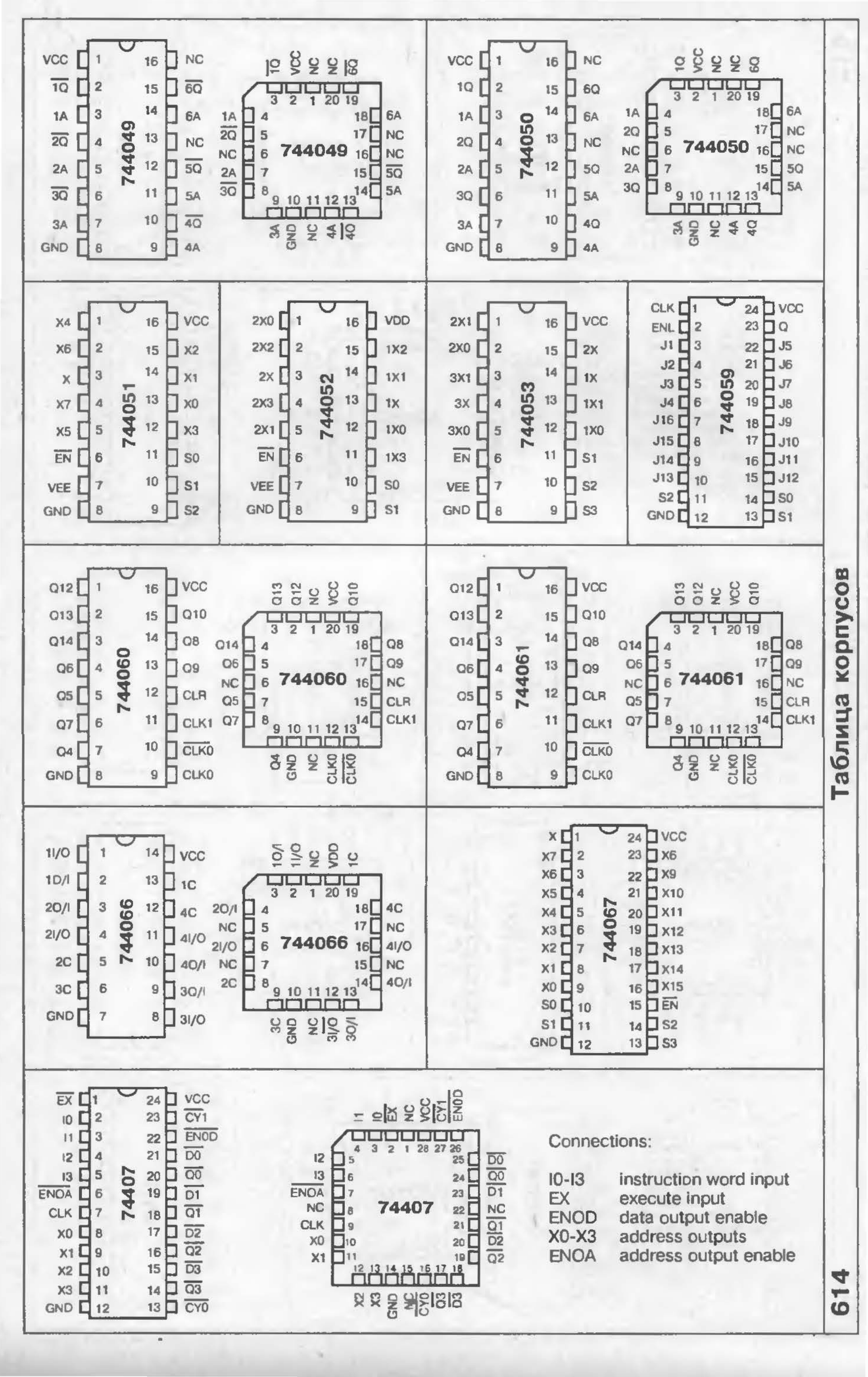

7436
1A 1 14 VCC
1B 2 13 4B
1Q 3 12 4A
2A 4 11 4Q
2B 5 10 3B
2Q 8 9 3A
GND 7 8 3Q
7436
1B 1A NC VCC 4B
3 2 1 20 19
1Q 4 18 4A
NC 5 17 NC
2A 6 16 4Q
NC 7 15 NC
2B 6 14 3B
9 10 11 12 13
2Q GND NC 3Q 3A
74362
LC1 1 20 VCC2(+5)
LC2 2 19 XTAL
GND1 3 18 XTAL
FFQ 4 17 DIN OSC
FFD 5 16 DOUT OSC
CLK4 TTL 6 15 CLK2 TTL
CLK3 TTL 7 14 CLK1 TTL
CLK3 8 13 VCC1 (+12)
CLK4 9 12 CLK1
GND2 10 11 CLK2
74363
ENO 1 20 VCC
Q0 2 19 Q7
D0 3 18 D7
D1 4 17 D6
Q1 5 16 Q6
Q2 6 15 Q5
D2 7 14 D5
D3 8 13 D4
Q3 9 12 Q4
GND 10 11 ENL
74364
ENO 1 20 VCC
Q0 2 19 Q7
D0 3 16 D7
D1 4 17 D6
Q1 5 16 Q6
Q2 6 15 Q5
D2 7 14 D5
D3 8 13 D4
Q3 9 12 Q4
GND 10 11 CLK
74365
EN1 1 16 VCC
D0 2 15 EN2
Q0 3 14 D5
D1 4 13 Q5
Q1 5 12 D4
D2 8 11 Q4
Q2 7 10 D3
GND 6 9 Q3
74365
D0 EN1 NC VCC EN2
3 2 1 20 19
Q0 4 16 D5
D1 5 17 Q5
NC 6 16 NC
Q1 7 15 D4
D2 6 14 Q4
9 10 11 12 13
Q2 GND NC Q3 D3
74366
EN1 1 16 VCC
D0 2 15 EN2
Q0 3 14 D5
D1 4 13 Q5
Q1 5 12 D4
D2 6 11 Q4
Q2 7 10 D3
GND 8 9 Q3
74366
D0 EN1 NC VCC EN2
3 2 1 20 19
Q0 4 16 D5
D1 5 17 Q5
NC 6 16 NC
Q1 7 15 D4
D2 8 14 Q4
9 10 11 12 13
Q2 GND NC Q3 D3
74367
EN1 1 16 VCC
D0 2 15 EN2
Q0 3 14 D5
D1 4 13 Q5
Q1 5 12 D4
D2 6 11 Q4
Q2 7 10 D3
GND 8 9 Q3
74367
D0 EN1 NC VCC EN2
3 2 1 20 19
Q0 4 16 D5
D1 5 17 Q5
NC 6 16 NC
Q1 7 15 D4
D2 8 14 Q4
9 10 11 12 13
Q2 GND NC Q3 D3
74368
EN1 1 16 VCC
D0 2 15 EN2
Q0 3 14 D5
D1 4 13 Q5
Q1 5 12 D4
D2 6 11 Q4
Q2 7 10 D3
GND 6 9 Q3
74368
D0 EN1 NC VCC EN2
3 2 1 20 19
Q0 4 18 D5
D1 5 17 Q5
NC 6 16 NC
Q1 7 15 D4
D2 8 14 Q4
9 10 11 12 13
Q2 GND NC Q3 D3
7437
1B 1 14 VCC
1A 2 13 4B
1Q 3 12 4A
2B 4 11 4Q
2A 5 10 3B
2Q 8 9 3A
GND 7 6 3Q
7437
1A 1B NC VCC 4B
3 2 1 20 19
1Q 4 18 4A
NC 5 17 NC
2B 6 16 4Q
NC 7 15 NC
2A 8 14 3B
9 10 11 12 13
2Q GND NC 3Q 3A
74370
A6 1 16 VCC
A5 2 15 A7
A4 3 14 A8
A3 4 13 EN
A0 5 12 D0
A1 6 11 Q1
A2 7 10 Q2
GND 8 9 Q3
74371
A0 1 20 VCC
A1 2 19 A7
A2 3 16 A6
A3 4 17 A5
A4 5 16 EN2
Q0 8 15 EN1
Q1 7 14 Q7
Q2 8 13 Q6
Q3 9 12 Q5
GND 10 11 Q4
74373
ENO 1 20 VCC
Q0 2 19 Q7
D0 3 18 D7
D1 4 17 D6
Q1 5 16 Q6
Q2 6 15 Q5
D2 7 14 D5
D3 8 13 D4
Q3 9 12 Q4
GND 10 11 ENL
74373
D0 Q0 ENO VCC Q7
3 2 1 20 19
D1 4 18 D7
Q1 5 17 D6
Q2 6 16 Q6
D2 7 15 Q5
D3 8 14 D5
9 10 11 12 13
Q3 GND ENL Q4 D4


74374
END 1, Q0 2, D0 3, D1 4, Q1 5, Q2 6, D2 7, D3 8, Q3 9, GND 10, CLK 11, Q4 12, D4 13, D5 14, Q5 15, Q6 16, D6 17, D7 18, Q7 19, VCC 20
74375
1D 1, 1Q 2, 1Q 3, 1EN, 2EN 4, 2Q 5, 2Q 6, 2D 7, GND 8, 3D 9, 3Q 10, 3Q 11, 3EN, 4EN 12, 4Q 13, 4Q 14, 4D 15, VCC 16
74376
CLR 1, 1J 2, 1K 3, 1Q 4, 2Q 5, 2K 6, 2J 7, GND 8, CLK 9, 3J 10, 3K 11, 3Q 12, 4Q 13, 4K 14, 4J 15, VCC 16
74377
ENO 1, Q0 2, D0 3, D1 4, Q1 5, Q2 6, D2 7, D3 8, Q3 9, GND 10, CLK 11, Q4 12, D4 13, D5 14, Q5 15, Q6 16, D6 17, D7 18, Q7 19, VCC 20
74378
ENO 1, Q0 2, D0 3, D1 4, Q1 5, D2 6, Q2 7, GND 8, CLK 9, Q3 10, D3 11, Q4 12, D4 13, D5 14, Q5 15, VCC 16
74379
EN 1, Q0 2, Q0 3, D0 4, D1 5, Q1 6, Q1 7, GND 8, CLK 9, Q2 10, Q2 11, D2 12, D3 13, Q3 14, Q3 15, VCC 16
7438
1B 1, 1A 2, 1Q 3, 2B 4, 2A 5, 2Q 6, GND 7, 3Q 8, 3A 9, 3B 10, 4Q 11, 4A 12, 4B 13, VCC 14
74380
CLK 1, LOAD 2, D0 3, D1 4, D2 5, D3 6, D4 7, D5 8, D6 9, D7 10, PDL 11, CND 12, EN 13, S 14, Q7 15, Q6 16, Q5 17, Q4 18, Q3 19, Q2 20, Q1 21, Q0 22, CLR 23, VCC 24
74381
A1 1, B1 2, A0 3, B0 4, S0 5, S1 6, S2 7, Q0 8, Q1 9, GND 10, Q2 11, Q3 12, G 13, P 14, CYn 15, B3 16, A3 17, B2 18, A2 19, VCC 20
74382
A1 1, B1 2, A0 3, B0 4, S0 5, S1 8, S2 7, Q0 8, Q1 9, GND 10, Q2 11, Q3 12, DVR 13, CYn+4 14, CYn 15, B3 16, A3 17, B2 18, A2 19, VCC 20
74384
CLR 1, X3 2, X2 3, X1 4, X0 5, PROD 6, CLK 7, GND 8, MODE 9, K 10, X7 11, X6 12, X5 13, X4 14, Y 15, VCC 16


74385
CLK 1, 1SUM 2, 1S/Ā 3, 1B 4, 1A 5, 2A 6, 2B 7, 2S/Ā 8, SUM 9, GND 10, CLR 11, 3SUM 12, 3S/Ā 13, 3B 14, 3A 15, 4A 16, 4B 17, 4S/Ā 18, 4SUM 19, VCC 20
74386
1A 1, 1B 2, 1Q 3, 2Q 4, 2B 5, 2A 6, GND 7, 3A 8, 3B 9, 3Q 10, 4Q 11, 4B 12, 4A 13, VCC 14
74387
A6 1, A5 2, A4 3, A3 4, A0 5, A1 6, A2 7, GND 8, Q3 9, Q2 10, Q1 11, Q0 12, EN1 13, EN2 14, A7 15, VCC 16
74389
SEL A/B 1, Q0 2, Q0 3, A0 4, B0 5, B1 6, A1 7, Q1 8, Q1 9, GND 10, CLK 11, Q2 12, Q2 13, A2 14, B2 15, B3 16, A3 17, Q3 18, Q3 19, VCC 20
743893
R0 D0 VCC BG GND BUS GND
D1 4, R1 5, LOGIC GND 6, D2 7, R2 8, D3 R3 DE RE BUS GND, I/O3 14, I/O2 15, BUS GND 16, I/O1 17, I/O0 18
7439
1Q 1, 1A 2, 1B 3, 2Q 4, 2A 5, 2B 6, GND 7, 3B 8, 3A 9, 3Q 10, 4B 11, 4A 12, 4Q 13, VCC 14
74390
1A 1, 1CLR 2, 1Q0 3, 1B 4, 1Q1 5, 1Q2 6, 1Q3 7, GND 8, 2Q3 9, 2Q2 10, 2Q1 11, 2B 12, 2Q0 13, 2CLR 14, 2A 15, VCC 16
74393
1A 1, 1CLR 2, 1Q0 3, 1Q1 4, 1Q2 5, 1Q3 6, GND 7, 2Q3 8, 2Q2 9, 2Q1 10, 2Q0 11, 2CLR 12, 2A 13, VCC 14
74395
CLR 1, DS 2, D0 3, D1 4, D2 5, D3 6, S/L 7, GND 8, EN 9, CLK 10, QS 11, Q3 12, Q2 13, Q1 14, Q0 15, VCC 16
74396
2Q0 1, 1Q0 2, D0 3, 2Q1 4, 1Q1 5, D1 6, CLK 7, GND 8, D2 9, 1Q2 10, 2Q2 11, D3 12, 1Q3 13, 2Q3 14, EN 15, VCC 16
74398
SEL Ā/B 1, Q0 2, Q0 3, A0 4, B0 5, B1 6, A1 7, Q1 8, Q1 9, GND 10, CLK 11, Q2 12, Q2 13, A2 14, B2 15, B3 16, A3 17, Q3 18, Q3 19, VCC 20


74399
74399
7440/1
7440/1
7440/2
74400
744002
744002
74401/1
74401/2
74401/2
7440102
7440103
7440103
7440104
7440102
7440105
744015
744016
744017


74402
Connections:
S0-S3 polynomial select
CWG check word generate input
D/CW serial data/check input
D date input
QER error output
RO register output
SEI serial expansion input
RFB register feedback
S preset
744020
744022
744024
744028
74403
Connections:
ENOS serial output enable
CPSI serial input clock
IES serial input enable
TTS transfer to stack
TOS transfer to serial
IRF input register full
CPSD serial output clock
PL parallel load input
TDP transfer out parallel
DRE output register empty
744040
744046


744049
744049
744050
744050
744051
744052
744053
744059
744060
744060
744061
744061
744066
744066
744067
74407
74407
Connections:
I0-I3 instruction word input
EX execute input
ENOD data output enable
X0-X3 address outputs
ENOA address output enable

744072

DIP:

Pin	Signal	Pin	Signal
1	1Q	14	VCC
2	1A	13	2Q
3	1B	12	2A
4	1C	11	2B
5	1D	10	2C
8	NC	9	2D
7	GND	8	NC

PLCC:

Pin	Signal	Pin	Signal	Pin	Signal	Pin	Signal
3	1A	4	1B	18	2A	9	NC
2	1Q	5	NC	17	NC	10	GND
1	NC	6	1C	16	2B	11	NC
20	VCC	7	NC	15	NC	12	NC
19	2Q	8	1D	14	2C	13	2D

744075

DIP:

Pin	Signal	Pin	Signal
1	1A	14	VCC
2	1B	13	3C
3	2A	12	3A
4	2B	11	3B
5	2C	10	3Q
6	2Q	9	1Q
7	GND	8	1C

PLCC:

Pin	Signal	Pin	Signal	Pin	Signal	Pin	Signal
3	1B	4	2A	18	3B	9	2Q
2	1A	5	NC	17	NC	10	GND
1	NC	6	2B	16	3A	11	NC
20	VCC	7	NC	15	NC	12	1C
19	3C	8	2C	14	3Q	13	1Q

744078

DIP:

Pin	Signal	Pin	Signal
1	Q	14	VCC
2	A	13	$\overline{Q}$
3	B	12	H
4	C	11	G
5	D	10	F
6	NC	9	E
7	GND	8	NC

PLCC:

Pin	Signal	Pin	Signal	Pin	Signal	Pin	Signal
3	A	4	B	16	H	9	NC
2	Q	5	NC	17	NC	10	GND
1	NC	6	C	16	G	11	NC
20	VCC	7	NC	15	NC	12	NC
19	$\overline{Q}$	8	D	14	NC	13	E

744094

DIP:

Pin	Signal	Pin	Signal
1	STR	16	VCC
2	DS	15	ENO
3	CLK	14	Q4
4	Q0	13	Q5
5	Q1	12	Q6
6	Q2	11	Q7
7	Q3	10	$\overline{QS'}$
8	GND	9	QS'

PLCC:

Pin	Signal	Pin	Signal	Pin	Signal	Pin	Signal
3	DS	4	CLK	18	Q4	9	Q3
2	STR	5	Q0	17	Q5	10	GND
1	NC	6	NC	16	NC	11	NC
20	VCC	7	Q1	15	Q6	12	QS'
19	ENO	8	Q2	14	Q7	13	$\overline{QS'}$

7441

DIP:

Pin	Signal	Pin	Signal
1	8	16	0
2	9	15	1
3	D0	14	5
4	D3	13	4
5	VCC	12	GND
6	D1	11	6
7	D2	10	7
6	2	9	3

74410

DIP:

Pin	Signal	Pin	Signal
1	$\overline{CS}$	18	VCC
2	$\overline{WE}$	17	D0
3	A0	16	Q0
4	A1	15	D1
5	A2	14	Q1
6	A3	13	D2
7	CLK	12	Q2
8	$\overline{ENO}$	11	D3
9	GND	10	Q3

PLCC:

Pin	Signal	Pin	Signal	Pin	Signal	Pin	Signal
3	A0	4	A1	18	Q0	9	$\overline{ENO}$
2	$\overline{WE}$	5	A2	17	D1	10	GND
1	$\overline{CS}$	6	NC	16	NC	11	Q3
20	VCC	7	A3	15	Q1	12	D3
19	D0	8	CLK	14	D2	13	Q2

74412

DIP:

Pin	Signal	Pin	Signal
1	$\overline{SEL1}$	24	VCC
2	MODE	23	$\overline{INT}$
3	D0	22	D7
4	Q0	21	Q7
5	D1	20	D6
6	Q1	19	Q6
7	D2	18	D5
8	Q2	17	Q5
9	D3	16	D4
10	Q3	15	Q4
11	STR	14	$\overline{CLR}$
12	GND	13	SEL2

74413

DIP:

Pin	Signal	Pin	Signal
1	NC	16	VCC
2	IR	15	S0
3	S1	14	OR
4	D0	13	Q0
5	D1	12	Q1
6	D2	11	Q2
7	D3	10	Q3
8	GND	9	$\overline{RST}$

PLCC:

Pin	Signal	Pin	Signal	Pin	Signal	Pin	Signal
3	IR	4	S1	18	OR	9	D3
2	NC	5	D0	17	Q0	10	GND
1	NC	6	NC	16	NC	11	NC
20	VCC	7	D1	15	Q1	12	$\overline{RST}$
19	S0	6	D2	14	Q2	13	Q3

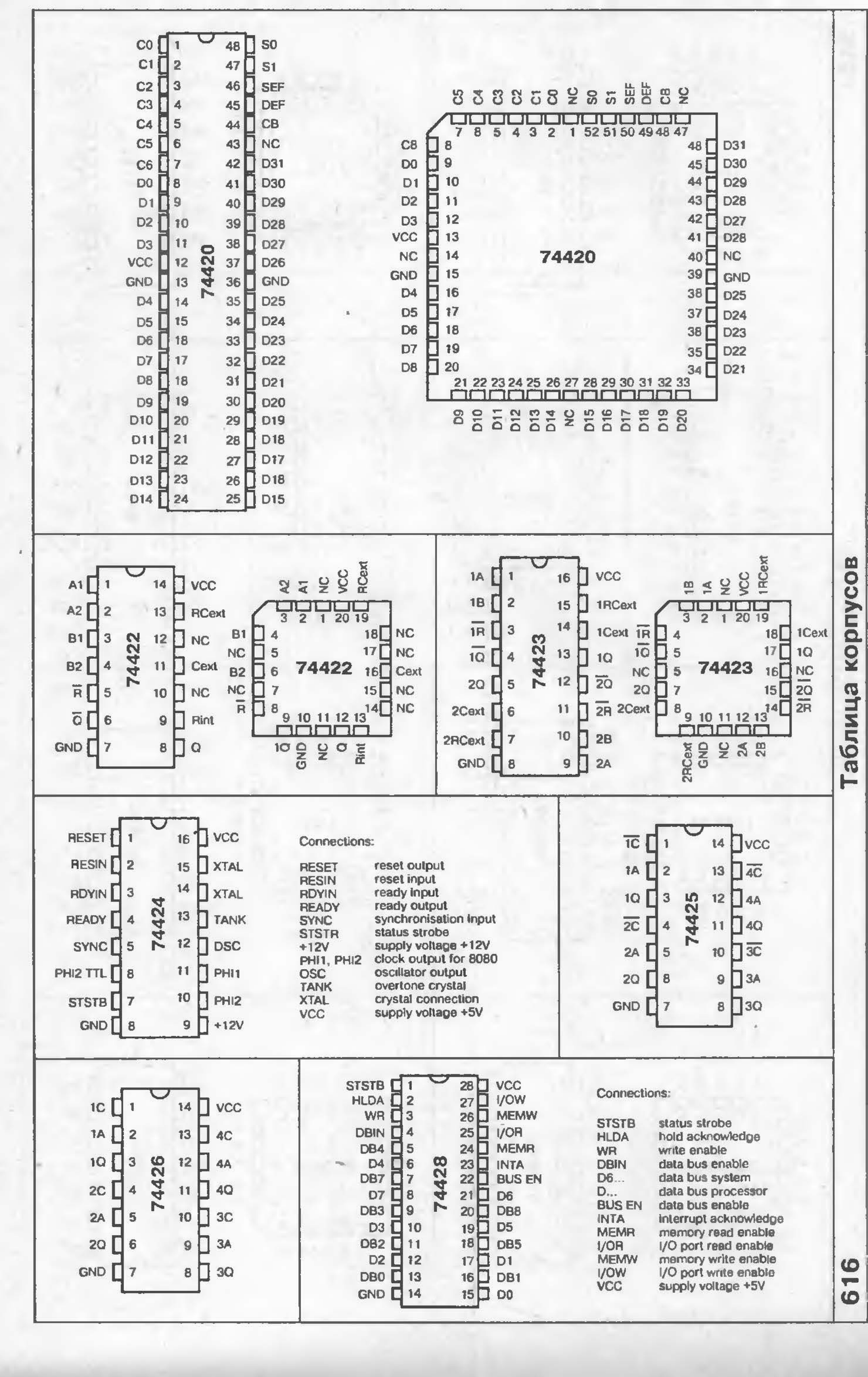
7442

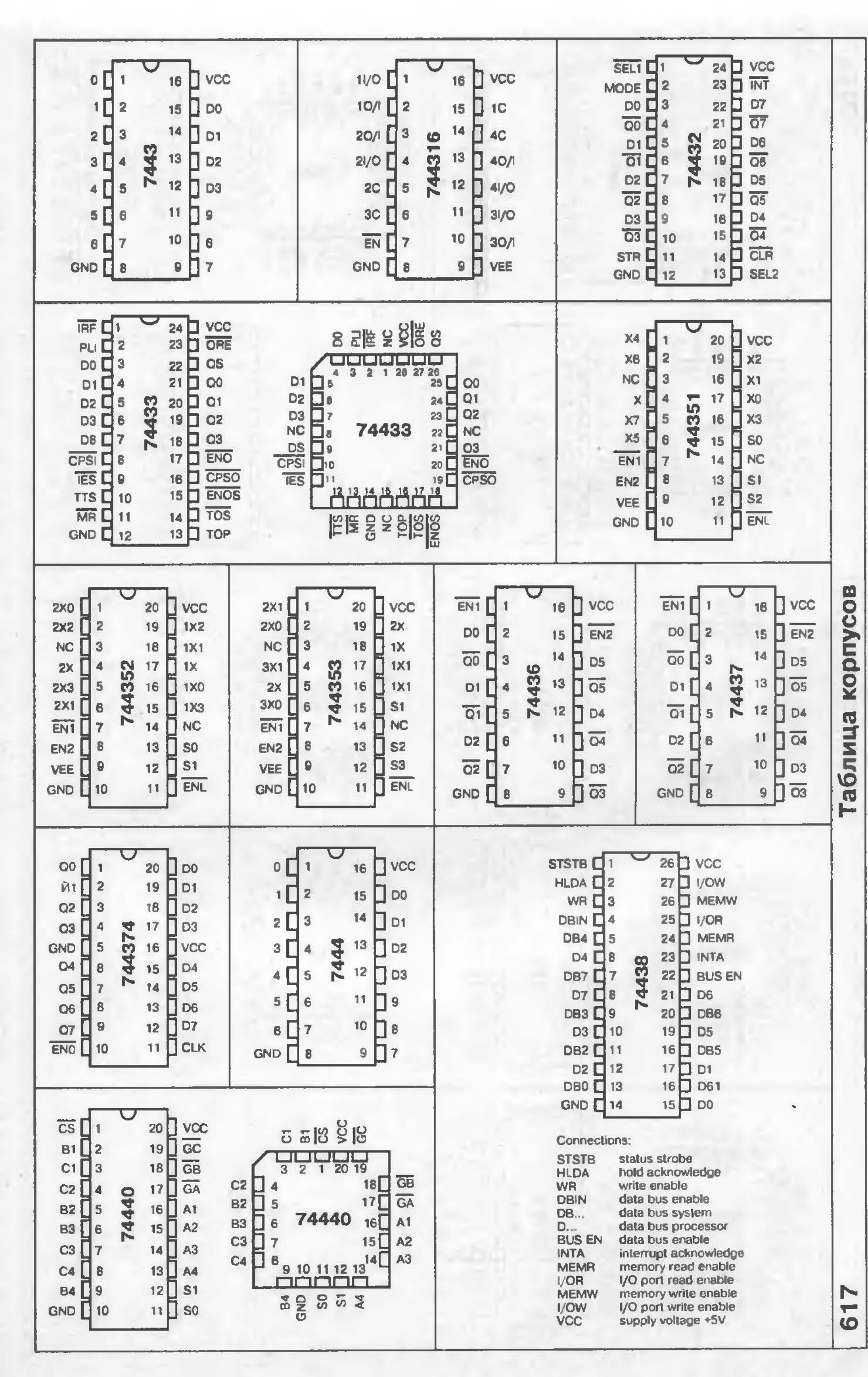
DIP:

Pin	Signal	Pin	Signal
1	0	16	VCC
2	1	15	D0
3	2	14	D1
4	3	13	D2
5	4	12	D3
6	5	11	9
7	6	10	8
6	GND	9	7

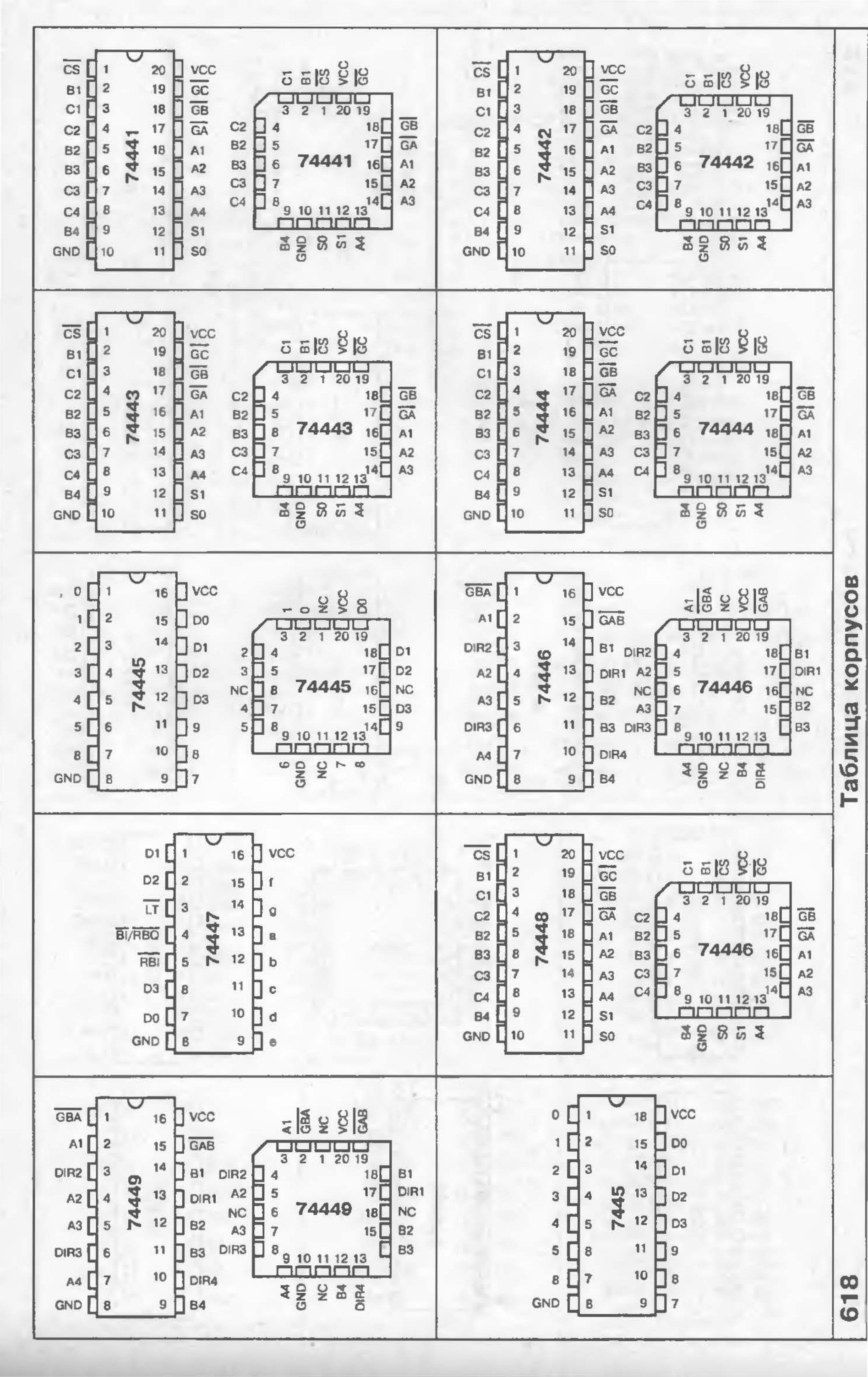
PLCC:

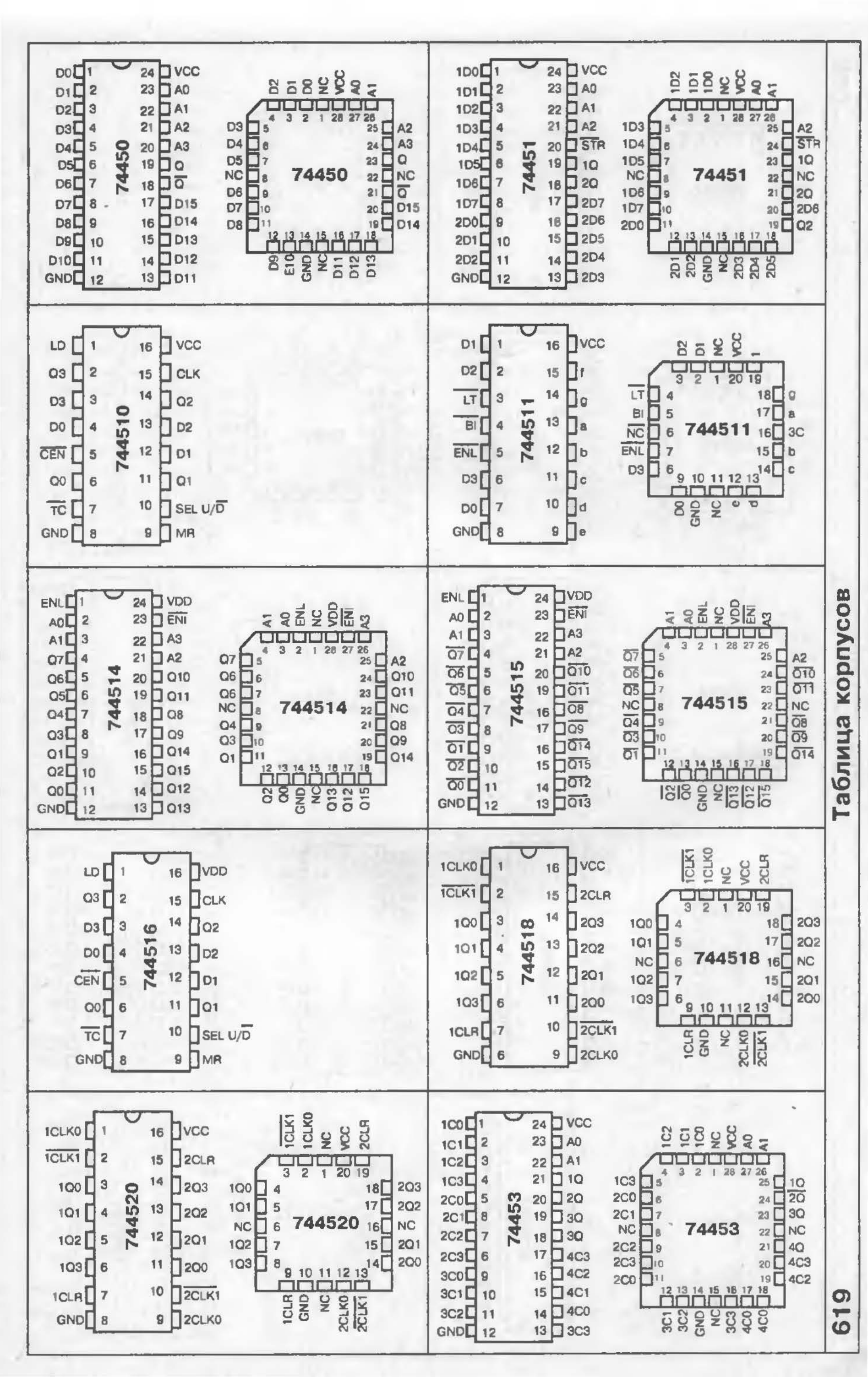
Pin	Signal	Pin	Signal	Pin	Signal	Pin	Signal
3	1	4	2	18	D1	9	6
2	0	5	3	17	D2	10	GND
1	NC	8	NC	16	NC	11	NC
20	VCC	7	4	15	D3	12	7
19	D0	8	5	14	9	13	8


74420
C0 1 48 S0
C1 2 47 S1
C2 3 46 SEF
C3 4 45 DEF
C4 5 44 CB
C5 6 43 NC
C6 7 42 D31
D0 8 41 D30
D1 9 40 D29
D2 10 39 D28
D3 11 38 D27
VCC 12 37 D26
GND 13 36 GND
D4 14 35 D25
D5 15 34 D24
D6 18 33 D23
D7 17 32 D22
D8 18 31 D21
D9 19 30 D20
D10 20 29 D19
D11 21 28 D18
D12 22 27 D17
D13 23 26 D18
D14 24 25 D15
74420
C5 C4 C3 C2 C1 C0 NC S0 S1 SEF DEF CB NC
7 8 5 4 3 2 1 52 51 50 49 48 47
C8 8 48 D31
D0 9 45 D30
D1 10 44 D29
D2 11 43 D28
D3 12 42 D27
VCC 13 41 D28
NC 14 40 NC
GND 15 39 GND
D4 16 38 D25
D5 17 37 D24
D6 18 38 D23
D7 19 35 D22
D8 20 34 D21
21 22 23 24 25 26 27 28 29 30 31 32 33
D9 D10 D11 D12 D13 D14 NC D15 D16 D17 D18 D19 D20
74422
A1 1 14 VCC
A2 2 13 RCext
B1 3 12 NC
B2 4 11 Cext
R̄ 5 10 NC
Q̄ 6 9 Rint
GND 7 8 Q
74422
A2 A1 NC VCC RCext
3 2 1 20 19
B1 4 18 NC
NC 5 17 NC
B2 6 16 Cext
NC 7 15 NC
R̄ 8 14 NC
9 10 11 12 13
1Q̄ GND NC Q Rint
74423
1A 1 16 VCC
1B 2 15 1RCext
1R̄ 3 14 1Cext
1Q̄ 4 13 1Q
2Q 5 12 2Q̄
2Cext 6 11 2R̄
2RCext 7 10 2B
GND 8 9 2A
74423
1B 1A NC VCC 1RCext
3 2 1 20 19
1R̄ 4 18 1Cext
1Q̄ 5 17 1Q
NC 5 16 NC
2Q 7 15 2Q̄
2Cext 8 14 2R̄
9 10 11 12 13
2RCext GND NC 2A 2B
74424
RESET 1 16 VCC
RESIN 2 15 XTAL
RDYIN 3 14 XTAL
READY 4 13 TANK
SYNC 5 12 DSC
PHI2 TTL 8 11 PHI1
STSTB 7 10 PHI2
GND 8 9 +12V
Connections:
RESET reset output
RESIN reset input
RDYIN ready input
READY ready output
SYNC synchronisation input
STSTR status strobe
+12V supply voltage +12V
PHI1, PHI2 clock output for 8080
OSC oscillator output
TANK overtone crystal
XTAL crystal connection
VCC supply voltage +5V
74425
1C̄ 1 14 VCC
1A 2 13 4C̄
1Q 3 12 4A
2C̄ 4 11 4Q
2A 5 10 3C̄
2Q 8 9 3A
GND 7 8 3Q
74426
1C 1 14 VCC
1A 2 13 4C
1Q 3 12 4A
2C 4 11 4Q
2A 5 10 3C
2Q 6 9 3A
GND 7 8 3Q
74428
STSTB 1 28 VCC
HLDA 2 27 I/OW
WR 3 26 MEMW
DBIN 4 25 I/OR
DB4 5 24 MEMR
D4 6 23 INTA
DB7 7 22 BUS EN
D7 8 21 D6
DB3 9 20 DB8
D3 10 19 D5
DB2 11 18 DB5
D2 12 17 D1
DB0 13 16 DB1
GND 14 15 D0
Connections:
STSTB status strobe
HLDA hold acknowledge
WR write enable
DBIN data bus enable
D6... data bus system
D... data bus processor
BUS EN data bus enable
INTA interrupt acknowledge
MEMR memory read enable
I/OR I/O port read enable
MEMW memory write enable
I/OW I/O port write enable
VCC supply voltage +5V



7443
744316
74432
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74433
744351
744352
744353
74436
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744374
7444
74438
74440
74440
Connections:
STSTB status strobe
HLDA hold acknowledge
WR write enable
DBIN data bus enable
DB... data bus system
D... data bus processor
BUS EN data bus enable
INTA interrupt acknowledge
MEMR memory read enable
I/OR I/O port read enable
MEMW memory write enable
I/OW I/O port write enable
VCC supply voltage +5V


74441
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744510
744511
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744518
744520
74453

744538 (DIP)

Pin	Signal	Pin	Signal
1	1Cext1	16	VCC
2	1RCext2	15	2Cext1
3	$\overline{1R}$	14	2RCext2
4	1A1	13	$\overline{2R}$
5	$\overline{1A0}$	12	2A1
6	1Q	11	$\overline{2A0}$
7	1Q	10	2Q
8	GND	9	2Q

744538 (PLCC)

Pin	Signal	Pin	Signal
1	NC	11	NC
2	1Cext1	12	2Q
3	1RCext2	13	2Q
4	$\overline{1R}$	14	$\overline{2A0}$
5	1A1	15	2A1
6	NC	16	NC
7	$\overline{1A0}$	17	$\overline{2R}$
8	1Q	18	2RCext2
9	1Q	19	2Cext1
10	GND	20	VCC

744543 (DIP)

Pin	Signal	Pin	Signal
1	$\overline{ENL}$	16	VCC
2	D2	15	f
3	D1	14	g
4	D3	13	e
5	D0	12	d
6	PH	11	c
7	BI	10	b
8	GND	9	a

744543 (PLCC)

Pin	Signal	Pin	Signal
1	NC	11	NC
2	$\overline{ENL}$	12	a
3	D2	13	b
4	D1	14	c
5	D3	15	d
6	NC	16	NC
7	D0	17	e
8	PH	18	g
9	BI	19	f
10	GND	20	VCC

74455 / 74456

Pin	Signal	Pin	Signal
1	$\overline{EN1}$	24	Qodd
2	$\overline{EN2}$	23	Qeven
3	PI	22	Q0
4	D0	21	$\overline{Q1}$
5	D1	20	$\overline{Q2}$
6	D2	19	GND
7	VCC	18	GND
8	D3	17	$\overline{Q3}$
9	D4	16	$\overline{Q4}$
10	D5	15	$\overline{Q5}$
11	D6	14	$\overline{Q6}$
12	D7	13	$\overline{Q7}$

744581

Pin	Signal	Pin	Signal
1	$\overline{B0}$	24	VDD
2	$\overline{A0}$	23	$\overline{A1}$
3	S3	22	$\overline{B1}$
4	S2	21	$\overline{A2}$
5	S1	20	$\overline{B2}$
6	S0	19	$\overline{A3}$
7	CYn	18	$\overline{B3}$
8	BA	17	$\overline{G}$
9	Q0	16	CYn+4
10	$\overline{Q1}$	15	$\overline{P}$
11	$\overline{Q2}$	14	A=B
12	GND	13	$\overline{Q3}$

7446

Pin	Signal	Pin	Signal
1	D1	16	VCC
2	D2	15	f
3	$\overline{LT}$	14	g
4	$\overline{BI/RBO}$	13	a
5	$\overline{RBI}$	12	b
6	D3	11	c
7	D0	10	d
8	GND	9	e

74460 (DIP)

Pin	Signal	Pin	Signal
1	A0	24	VCC
2	B0	23	B9
3	A1	22	A9
4	B1	21	B8
5	A2	20	A8
6	B2	19	A<>B
7	A3	18	A=B
8	B3	17	B7
9	A4	16	A7
10	B4	15	B6
11	A5	14	A6
12	GND	13	B5

74460 (PLCC)

Pin	Signal	Pin	Signal
1	NC	15	NC
2	A0	16	B5
3	B0	17	A6
4	A1	18	B6
5	B1	19	A7
6	A2	20	B7
7	B2	21	A=B
8	NC	22	NC
9	A3	23	A<>B
10	B3	24	A8
11	A4	25	B8
12	B4	26	A9
13	A5	27	B9
14	GND	28	VCC

74461 (DIP)

Pin	Signal	Pin	Signal
1	CLK	24	VCC
2	S0	23	$\overline{CYI}$
3	D0	22	Q0
4	D1	21	Q1
5	D2	20	Q2
6	D3	19	Q3
7	D4	18	Q4
8	D5	17	Q5
9	D6	16	Q6
10	D7	15	Q7
11	S1	14	$\overline{CY0}$
12	GND	13	$\overline{EN0}$

74461 (PLCC)

Pin	Signal	Pin	Signal
1	NC	15	NC
2	CLK	16	$\overline{EN0}$
3	S0	17	$\overline{CY0}$
4	D0	18	Q7
5	D1	19	Q6
6	D2	20	Q5
7	D3	21	Q4
8	NC	22	NC
9	D4	23	Q3
10	D5	24	Q2
11	D6	25	Q1
12	D7	26	Q0
13	S1	27	$\overline{CYI}$
14	GND	28	VCC

74465 (DIP)

Pin	Signal	Pin	Signal
1	$\overline{EN1}$	20	VCC
2	D0	19	$\overline{EN2}$
3	Q0	18	D7
4	D1	17	Q7
5	Q1	16	D6
6	D2	15	Q6
7	Q2	14	D5
8	D3	13	Q5
9	Q3	12	D4
10	GND	11	Q4

74465 (PLCC)

Pin	Signal	Pin	Signal
1	$\overline{EN1}$	11	Q4
2	D0	12	D4
3	Q0	13	Q5
4	D1	14	D5
5	Q1	15	Q6
6	D2	16	D6
7	Q2	17	Q7
8	D3	18	D7
9	Q3	19	$\overline{EN2}$
10	GND	20	VCC

74466 (DIP)

Pin	Signal	Pin	Signal
1	$\overline{EN1}$	20	VCC
2	D0	19	$\overline{EN2}$
3	$\overline{Q0}$	18	D7
4	D1	17	$\overline{Q7}$
5	$\overline{Q1}$	16	D6
6	D2	15	$\overline{Q6}$
7	$\overline{Q2}$	14	D5
8	D3	13	$\overline{Q5}$
9	$\overline{Q3}$	12	D4
10	GND	11	$\overline{Q4}$

74466 (PLCC)

Pin	Signal	Pin	Signal
1	$\overline{EN1}$	11	$\overline{Q4}$
2	D0	12	D4
3	$\overline{Q0}$	13	$\overline{Q5}$
4	D1	14	D6
5	$\overline{Q1}$	15	$\overline{Q6}$
6	D2	16	D6
7	$\overline{Q3}$	17	$\overline{Q7}$
8	D3	18	D7
9	$\overline{Q3}$	19	$\overline{EN2}$
10	GND	20	VCC

74467 (DIP)

Pin	Signal	Pin	Signal
1	$\overline{EN1}$	20	VCC
2	D0	19	$\overline{EN2}$
3	Q0	18	D7
4	D1	17	Q7
5	Q1	16	D6
6	D2	15	Q6
7	Q2	14	D5
8	D3	13	Q5
9	Q3	12	D4
10	GND	11	Q4

74487 (PLCC)

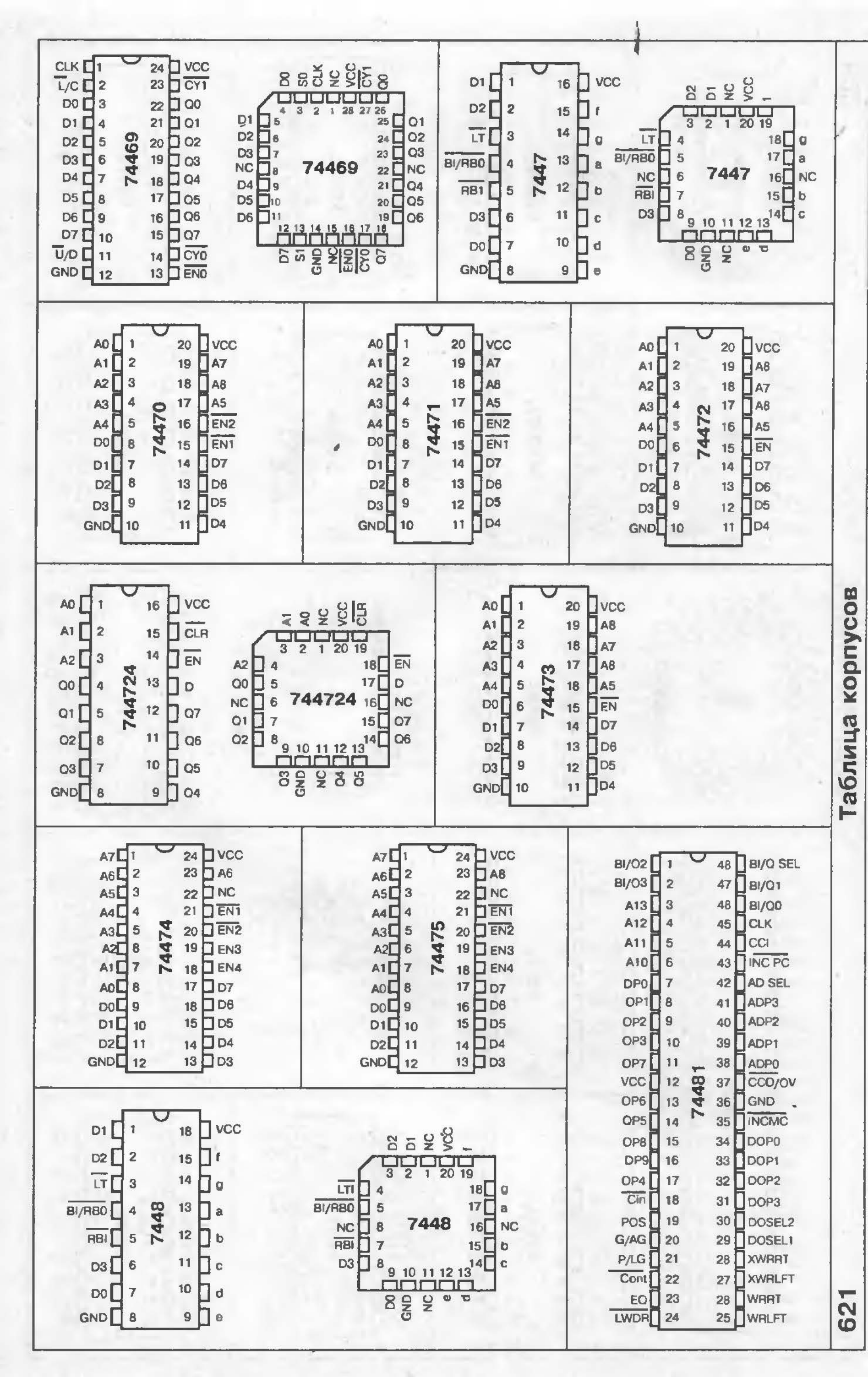
Pin	Signal	Pin	Signal
1	$\overline{EN1}$	11	Q4
2	D0	12	D4
3	Q0	13	Q5
4	D1	14	D6
5	Q1	15	Q6
6	D2	16	D6
7	Q2	17	Q7
8	D3	18	D7
9	Q3	19	$\overline{EN2}$
10	GND	20	VCC

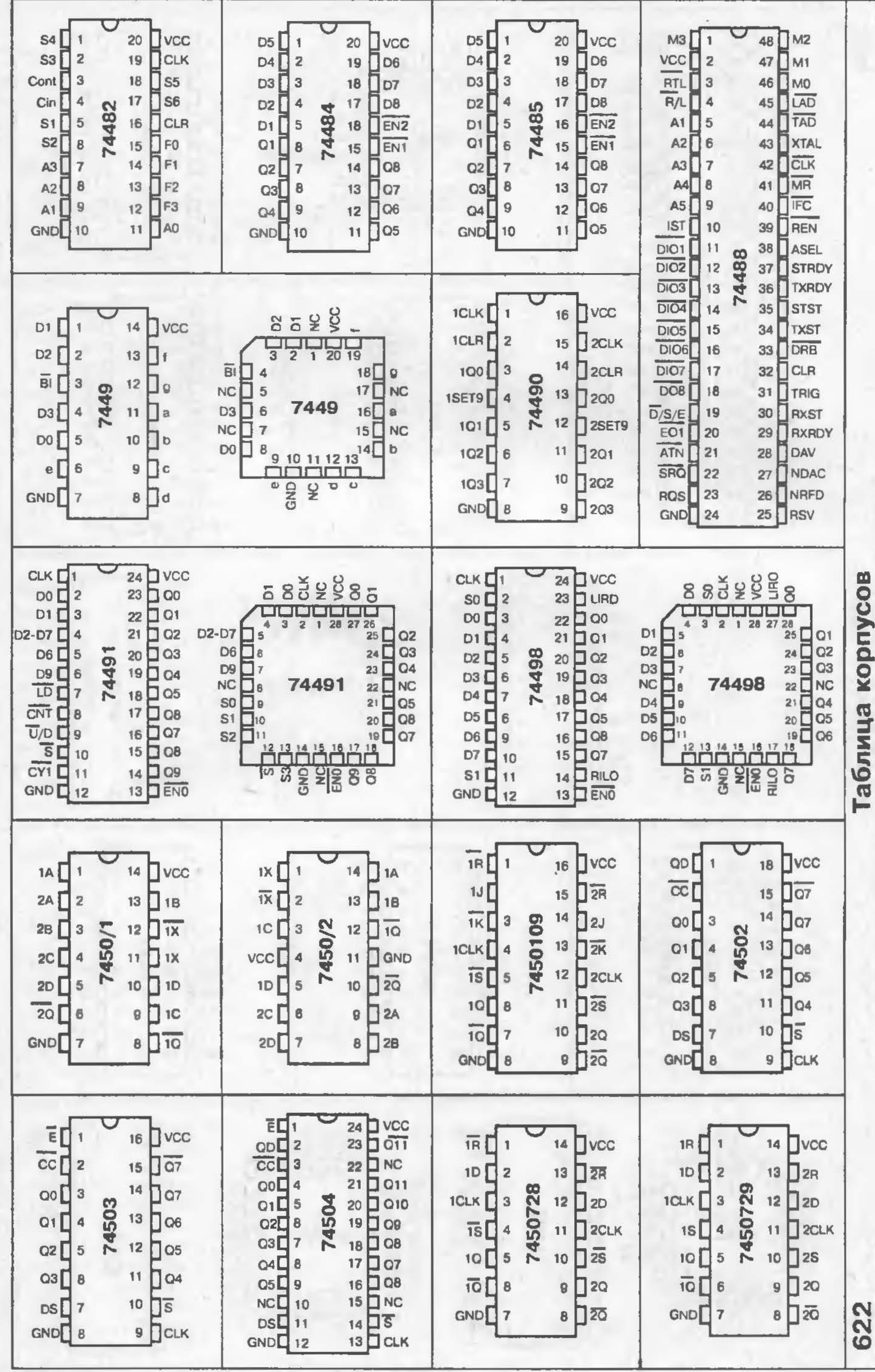
74468 (DIP)

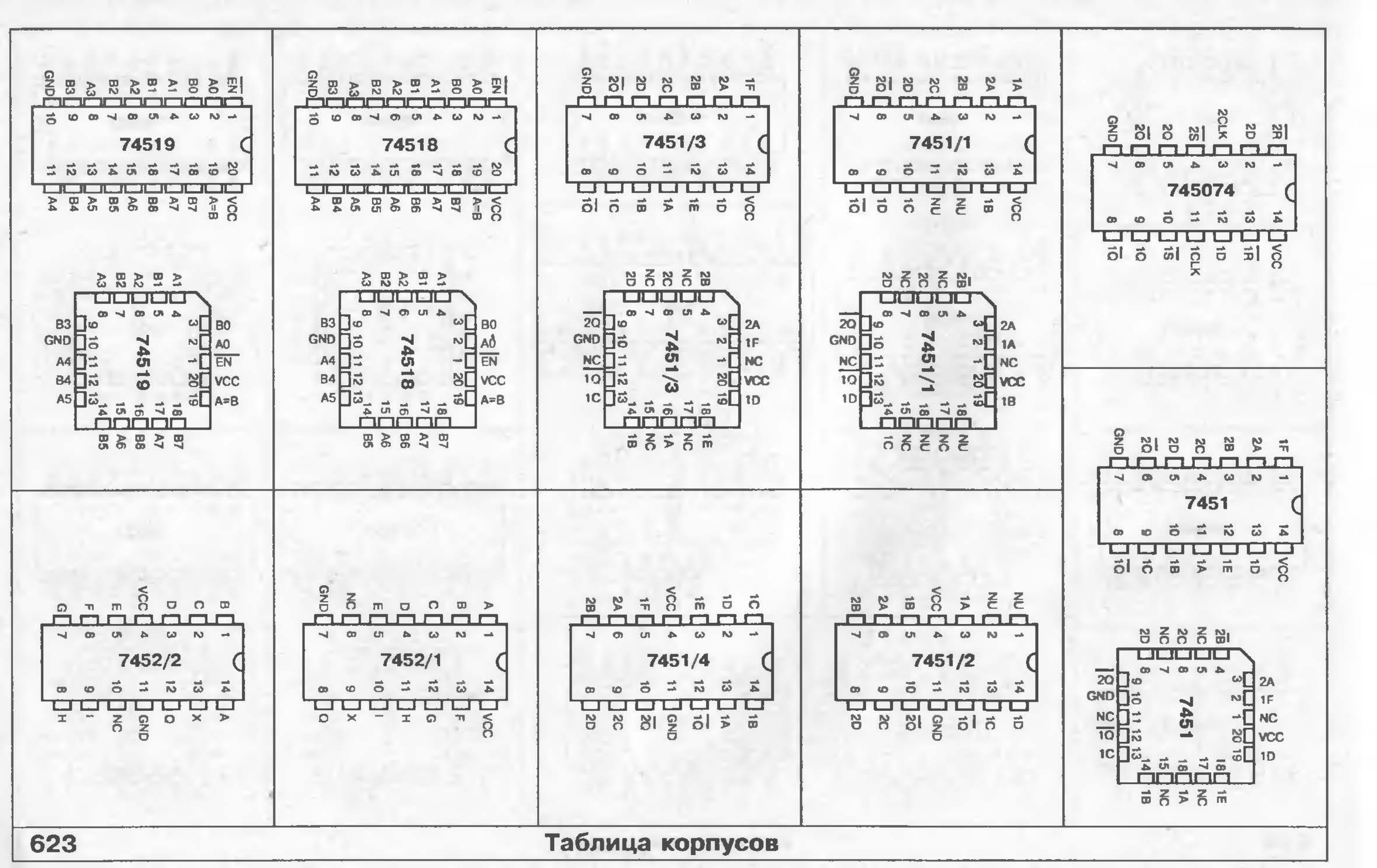
Pin	Signal	Pin	Signal
1	$\overline{EN1}$	20	VCC
2	D0	19	$\overline{EN2}$
3	$\overline{Q0}$	18	D7
4	D1	17	$\overline{Q7}$
5	$\overline{Q1}$	16	D6
6	D2	15	$\overline{Q6}$
7	$\overline{Q2}$	14	D5
8	D3	13	$\overline{Q5}$
9	$\overline{Q3}$	12	D4
10	GND	11	$\overline{Q4}$

74468 (PLCC)

Pin	Signal	Pin	Signal
1	$\overline{EN1}$	11	$\overline{Q4}$
2	D0	12	D4
3	$\overline{Q0}$	13	$\overline{Q5}$
4	D1	14	D5
5	$\overline{Q1}$	15	$\overline{Q6}$
6	D2	16	D6
7	$\overline{Q2}$	17	$\overline{Q7}$
8	D3	18	D7
9	$\overline{Q3}$	19	$\overline{EN2}$
10	GND	20	VCC


74469
CLK L/C D0 D1 D2 D3 D4 D5 D6 D7 U/D GND
VCC CY1 Q0 Q1 Q2 Q3 Q4 Q5 Q6 Q7 CY0 EN0
74469
D0 S0 CLK NC VCC CY1 Q0
D1 D2 D3 NC D4 D5 D6
Q1 Q2 Q3 NC Q4 Q5 Q6
D7 S1 GND NC EN0 CY0 Q7
7447
D1 D2 LT BI/RBO RBI D3 D0 GND
VCC f g a b c d e
7447
D2 D1 NC VCC f
LT BI/RBO NC RBI D3
g a NC b c
D0 GND NC e d
74470
A0 A1 A2 A3 A4 D0 D1 D2 D3 GND
VCC A7 A6 A5 EN2 EN1 D7 D6 D5 D4
74471
A0 A1 A2 A3 A4 D0 D1 D2 D3 GND
VCC A7 A6 A5 EN2 EN1 D7 D6 D5 D4
74472
A0 A1 A2 A3 A4 D0 D1 D2 D3 GND
VCC A8 A7 A6 A5 EN D7 D6 D5 D4
744724
A0 A1 A2 Q0 Q1 Q2 Q3 GND
VCC CLR EN D Q7 Q6 Q5 Q4
744724
A1 A0 NC VCC CLR
A2 Q0 NC Q1 Q2
EN D NC Q7 Q6
Q3 GND NC Q4 Q5
74473
A0 A1 A2 A3 A4 D0 D1 D2 D3 GND
VCC A8 A7 A6 A5 EN D7 D6 D5 D4
74474
A7 A6 A5 A4 A3 A2 A1 A0 D0 D1 D2 GND
VCC A6 NC EN1 EN2 EN3 EN4 D7 D6 D5 D4 D3
74475
A7 A6 A5 A4 A3 A2 A1 A0 D0 D1 D2 GND
VCC A8 NC EN1 EN2 EN3 EN4 D7 D6 D5 D4 D3
74481
BI/O2 BI/O3 A13 A12 A11 A10 DP0 OP1 OP2 OP3 OP7 VCC OP6 OP5 OP8 DP9 OP4 Cin POS G/AG P/LG Cont EQ LWDR
BI/Q SEL BI/Q1 BI/Q0 CLK CCI INC PC AD SEL ADP3 ADP2 ADP1 ADP0 CCO/OV GND INCMC DOP0 DOP1 DOP2 DOP3 DOSEL2 DOSEL1 XWRRT XWRLFT WRRT WRLFT
7448
D1 D2 LT BI/RBO RBI D3 D0 GND
VCC f g a b c d e
7448
D2 D1 NC VCC f
LTI BI/RBO NC RBI D3
g a NC b c
D0 GND NC e d


74482: 1 S4, 2 S3, 3 Cont, 4 Cin, 5 S1, 6 S2, 7 A3, 8 A2, 9 A1, 10 GND, 11 A0, 12 F3, 13 F2, 14 F1, 15 F0, 16 CLR, 17 S6, 18 S5, 19 CLK, 20 VCC
74484: 1 D5, 2 D4, 3 D3, 4 D2, 5 D1, 6 Q1, 7 Q2, 8 Q3, 9 Q4, 10 GND, 11 Q5, 12 Q6, 13 Q7, 14 Q8, 15 EN1, 16 EN2, 17 D8, 18 D7, 19 D6, 20 VCC
74485: 1 D5, 2 D4, 3 D3, 4 D2, 5 D1, 6 Q1, 7 Q2, 8 Q3, 9 Q4, 10 GND, 11 Q5, 12 Q6, 13 Q7, 14 Q8, 15 EN1, 16 EN2, 17 D8, 18 D7, 19 D6, 20 VCC
74488: 1 M3, 2 VCC, 3 RTL, 4 R/L, 5 A1, 6 A2, 7 A3, 8 A4, 9 A5, 10 IST, 11 DIO1, 12 DIO2, 13 DIO3, 14 DIO4, 15 DIO5, 16 DIO6, 17 DIO7, 18 DO8, 19 D/S/E, 20 EO1, 21 ATN, 22 SRQ, 23 RQS, 24 GND, 25 RSV, 26 NRFD, 27 NDAC, 28 DAV, 29 RXRDY, 30 RXST, 31 TRIG, 32 CLR, 33 DRB, 34 TXST, 35 STST, 36 TXRDY, 37 STRDY, 38 ASEL, 39 REN, 40 IFC, 41 MR, 42 CLK, 43 XTAL, 44 TAD, 45 LAD, 46 M0, 47 M1, 48 M2
7449: 1 D1, 2 D2, 3 BI, 4 D3, 5 D0, 6 e, 7 GND, 8 d, 9 c, 10 b, 11 a, 12 g, 13 f, 14 VCC
7449: 1 NC, 2 D1, 3 D2, 4 BI, 5 NC, 6 D3, 7 NC, 8 D0, 9 e, 10 GND, 11 NC, 12 d, 13 c, 14 b, 15 NC, 16 a, 17 NC, 18 g, 19 f, 20 VCC
74490: 1 1CLK, 2 1CLR, 3 1Q0, 4 1SET9, 5 1Q1, 6 1Q2, 7 1Q3, 8 GND, 9 2Q3, 10 2Q2, 11 2Q1, 12 2SET9, 13 2Q0, 14 2CLR, 15 2CLK, 16 VCC
74491: 1 CLK, 2 D0, 3 D1, 4 D2-D7, 5 D6, 6 D9, 7 LD, 8 CNT, 9 U/D, 10 S, 11 CY1, 12 GND, 13 EN0, 14 Q9, 15 Q8, 16 Q7, 17 Q8, 18 Q5, 19 Q4, 20 Q3, 21 Q2, 22 Q1, 23 Q0, 24 VCC
74491: 1 NC, 2 CLK, 3 D0, 4 D1, 5 D2-D7, 6 D6, 7 D9, 8 NC, 9 S0, 10 S1, 11 S2, 12 S, 13 S3, 14 GND, 15 NC, 16 EN0, 17 Q9, 18 Q8, 19 Q7, 20 Q8, 21 Q5, 22 NC, 23 Q4, 24 Q3, 25 Q2, 26 Q1, 27 Q0, 28 VCC
74498: 1 CLK, 2 S0, 3 D0, 4 D1, 5 D2, 6 D3, 7 D4, 8 D5, 9 D6, 10 D7, 11 S1, 12 GND, 13 EN0, 14 RILO, 15 Q7, 16 Q8, 17 Q5, 18 Q4, 19 Q3, 20 Q2, 21 Q1, 22 Q0, 23 LIRD, 24 VCC
74498: 1 NC, 2 CLK, 3 S0, 4 D0, 5 D1, 6 D2, 7 D3, 8 NC, 9 D4, 10 D5, 11 D6, 12 D7, 13 S1, 14 GND, 15 NC, 16 EN0, 17 RILO, 18 Q7, 19 Q6, 20 Q5, 21 Q4, 22 NC, 23 Q3, 24 Q2, 25 Q1, 26 Q0, 27 LIRO, 28 VCC
7450/1: 1 1A, 2 2A, 3 2B, 4 2C, 5 2D, 6 2Q, 7 GND, 8 1Q, 9 1C, 10 1D, 11 1X, 12 1X, 13 1B, 14 VCC
7450/2: 1 1X, 2 1X, 3 1C, 4 VCC, 5 1D, 6 2C, 7 2D, 8 2B, 9 2A, 10 2Q, 11 GND, 12 1Q, 13 1B, 14 1A
7450109: 1 1R, 1J, 3 1K, 4 1CLK, 5 1S, 6 1Q, 7 1Q, 8 GND, 9 2Q, 10 2Q, 11 2S, 12 2CLK, 13 2K, 14 2J, 15 2R, 16 VCC
74502: 1 QD, CC, 3 Q0, 4 Q1, 5 Q2, 6 Q3, 7 DS, 8 GND, 9 CLK, 10 S, 11 Q4, 12 Q5, 13 Q6, 14 Q7, 15 Q7, 18 VCC
74503: 1 E, 2 CC, 3 Q0, 4 Q1, 5 Q2, 6 Q3, 7 DS, 8 GND, 9 CLK, 10 S, 11 Q4, 12 Q5, 13 Q6, 14 Q7, 15 Q7, 16 VCC
74504: 1 E, 2 QD, 3 CC, 4 Q0, 5 Q1, 6 Q2, 7 Q3, 8 Q4, 9 Q5, 10 NC, 11 DS, 12 GND, 13 CLK, 14 S, 15 NC, 16 Q8, 17 Q7, 18 Q8, 19 Q9, 20 Q10, 21 Q11, 22 NC, 23 Q11, 24 VCC
7450728: 1 1R, 2 1D, 3 1CLK, 4 1S, 5 1Q, 6 1Q, 7 GND, 8 2Q, 9 2Q, 10 2S, 11 2CLK, 12 2D, 13 2R, 14 VCC
7450729: 1 1R, 2 1D, 3 1CLK, 4 1S, 5 1Q, 6 1Q, 7 GND, 8 2Q, 9 2Q, 10 2S, 11 2CLK, 12 2D, 13 2R, 14 VCC


74519
74518
7451/3
7451/1
745074
74519
74518
7451/3
7451/1
7451
7452/2
7452/1
7451/4
7451/2
7451

74520

$\overline{EN}$	1	20	VCC
A0	2	19	$\overline{A=B}$
B0	3	18	B7
A1	4	17	A7
B1	5	18	B6
A2	6	15	A6
B2	7	14	B5
A3	8	13	A5
B3	9	12	B4
GND	10	11	A4

74520 (PLCC): B0 3, A0 2, $\overline{EN}$ 1, VCC 20, $\overline{A=B}$ 19; A1 4, B1 5, A2 8, B2 7, A3 8; 18 B7, 17 A7, 16 B8, 15 A6, 14 B5; B3 9, GND 10, A4 11, B4 12, A5 13

74521

$\overline{EN}$	1	20	VCC
A0	2	19	A=B
B0	3	18	B7
A1	4	17	A7
B1	5	18	B8
A2	6	15	A6
B2	7	14	B5
A3	8	13	A5
B3	9	12	B4
GND	10	11	A4

74521 (PLCC): B0 3, A0 2, $\overline{EN}$ 1, VCC 20, A=B 19; A1 4, B1 5, A2 8, B2 7, A3 8; 18 B7, 17 A7, 16 B8, 15 A6, 14 B5; B3 9, GND 10, A4 11, B4 12, A5 13

74522

$\overline{EN}$	1	20	VCC
A0	2	19	$\overline{A=B}$
B0	3	18	B7
A1	4	17	A7
B1	5	16	B6
A2	8	15	A6
B2	7	14	B5
A3	8	13	A5
B3	9	12	B4
GND	10	11	A4

74522 (PLCC): B0 3, A0 2, $\overline{EN}$ 1, VCC 20, $\overline{A=B}$ 19; A1 4, B1 5, A2 6, B2 7, A3 8; 18 B7, 17 A7, 16 B6, 15 A6, 14 B5; B3 9, GND 10, A4 11, B4 12, A5 13

74524

S0	1	20	VCC
F0	2	19	S1
F1	3	18	$\overline{ENS}$
F2	4	17	C/SI
F3	5	16	C/SO
F4	6	15	EQ
F5	7	14	GT
F6	8	13	LT
F7	9	12	MODE
GND	10	11	CLK

74524 (PLCC): F1 3, F0 2, S0 1, VCC 20, S1 19; F2 4, F3 5, F4 6, F5 7, F6 8; 18 $\overline{ENS}$, 17 C/SI, 16 C/SO, 15 EQ, 14 GT; F7 9, GND 10, CLK 11, MODE 12, LT 13

745245

DIR	1	20	VCC
A0	2	19	$\overline{EN}$
A1	3	18	B0
A2	4	17	B1
A3	5	16	B2
A4	6	15	B3
A5	7	14	B4
A6	8	13	B5
A7	9	12	B6
GND	10	11	B7

74525

QZ/2	1	28	VCC
QZ	2	27	ST2
XTR	3	26	ST1
D0	4	25	ST0
D1	5	24	D15
D2	6	23	D14
D3	7	22	D13
D4	8	21	D12
D5	9	20	D11
D6	10	19	D10
D7	11	18	D9
$\overline{WE}$	12	17	D8
XTAL	13	16	$\overline{MR}$
GND	14	15	CLK

74525 (PLCC): D0 4, XTR 3, QZ 2, QZ/2 1, VCC 28, ST2 27, ST1 26; D1 5, D2 6, D3 7, D4 8, D5 9, D6 10, D7 11; 25 ST0, 24 D15, 23 D14, 22 D13, 21 D12, 20 D11, 19 D10; $\overline{WE}$ 12, XTAL 13, GND 14, CLK 15, $\overline{MR}$ 16, D8 17, D9 18

74526

$\overline{EN}$	1	20	VCC
D0	2	19	$\overline{D=P}$
D1	3	18	D15
D2	4	17	D14
D3	5	18	D13
D4	6	15	D12
D5	7	14	D11
D6	8	13	D10
D7	9	12	D9
GND	10	11	D8

74526 (PLCC): D1 3, D0 2, $\overline{EN}$ 1, VCC 20, $\overline{D=P}$ 19; D2 4, D3 5, D4 8, D5 7, D6 8; 18 D15, 17 D14, 16 D13, 15 D12, 14 D11; D7 9, GND 10, D8 11, D9 12, D10 13

74527

$\overline{EN}$	1	20	VCC
D0	2	19	$\overline{D=P}$
D1	3	18	P11
D2	4	17	D11
D3	5	16	P10
D4	8	15	D10
D5	7	14	P9
D6	8	13	D9
D7	9	12	P8
GND	10	11	D8

74527 (PLCC): D1 3, D0 2, $\overline{EN}$ 1, VCC 20, $\overline{D=P}$ 19; D2 4, D3 5, D4 8, D5 7, D8 8; 18 P11, 17 D11, 16 P10, 15 D10, 14 P9; D7 9, GND 10, D8 11, P8 12, D9 13

74528

$\overline{EN0}$	1	16	VCC
D0	2	15	$\overline{D=P}$
D1	3	14	D11
D2	4	13	D10
D3	5	12	D9
D4	6	11	D8
D5	7	10	D7
GND	8	9	D6

74528 (PLCC): D0 3, $\overline{EN0}$ 2, $\overline{NC}$ 1, VCC 20, $\overline{D=P}$ 19; D1 4, D2 5, NC 6, D3 7, D4 8; 18 D11, 17 D10, 16 NC, 15 D9, 14 D8; D5 9, GND 10, NC 11, D6 12, D7 13

7453/1

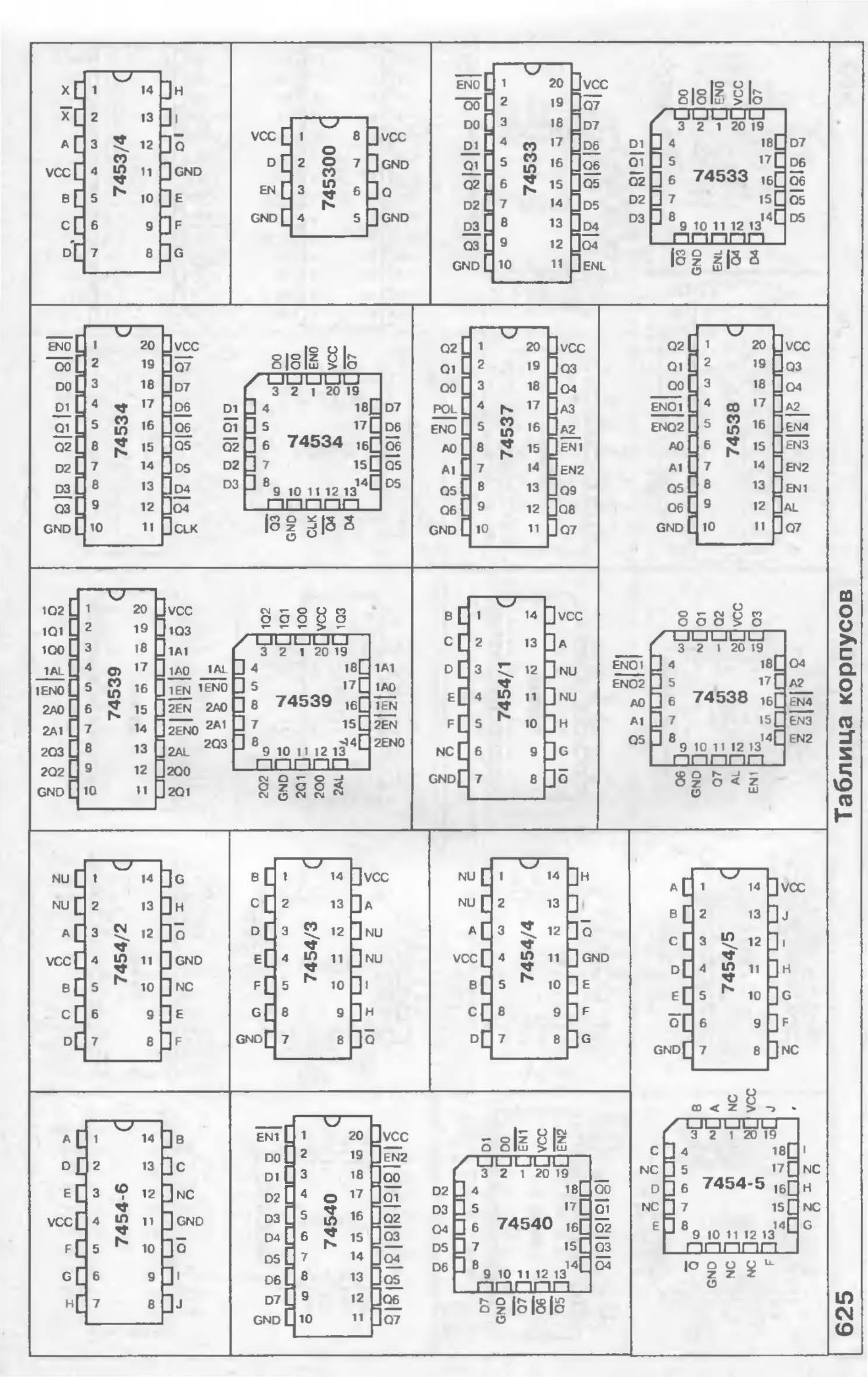
B	1	14	VCC
C	2	13	A
D	3	12	$\overline{X}$
E	4	11	X
F	5	10	H
NC	6	9	G
GND	7	8	$\overline{Q}$

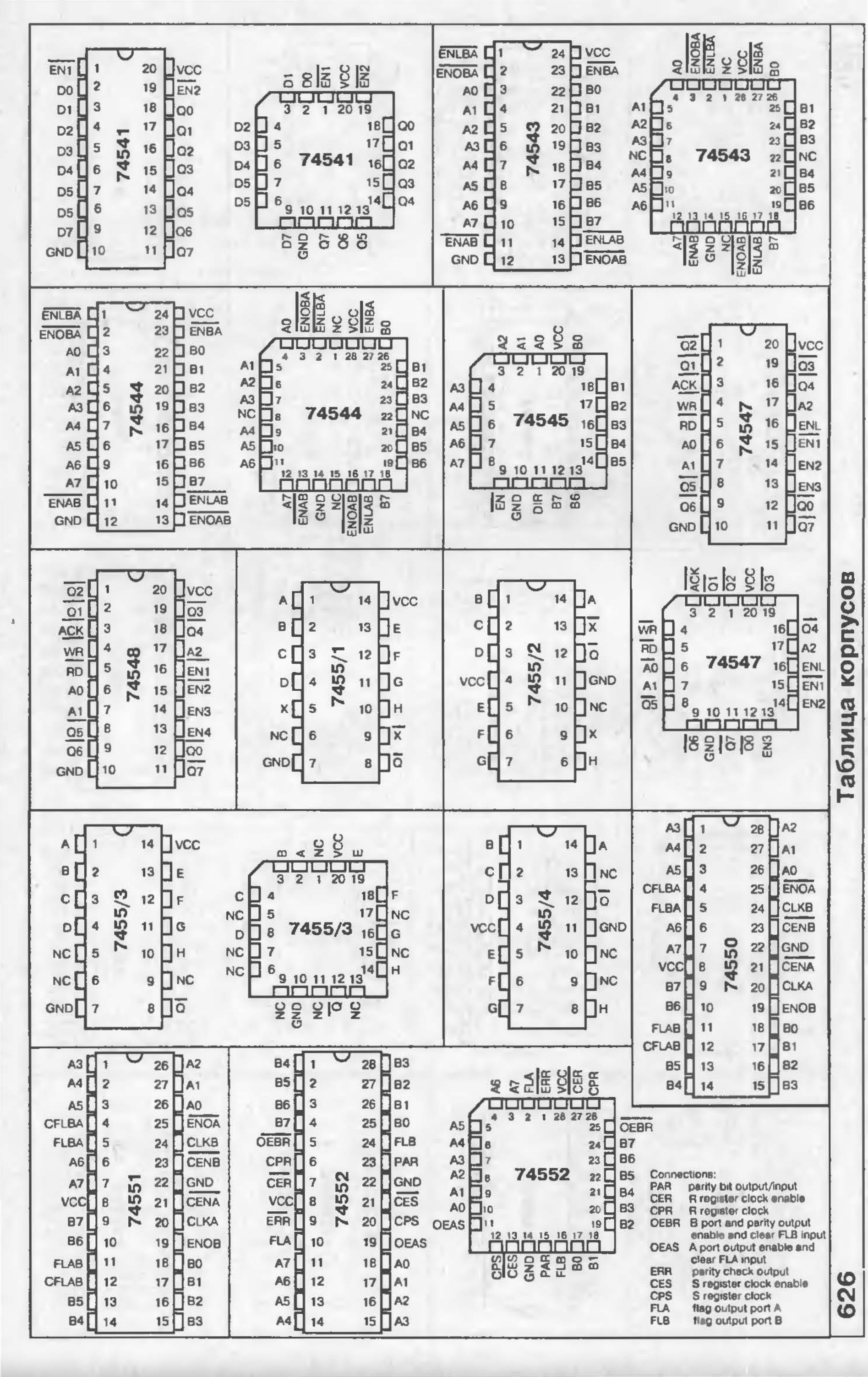
7453/2

X	1	14	G
$\overline{X}$	2	13	H
A	3	12	$\overline{Q}$
VCC	4	11	GND
B	5	10	NC
C	6	9	E
D	7	8	F

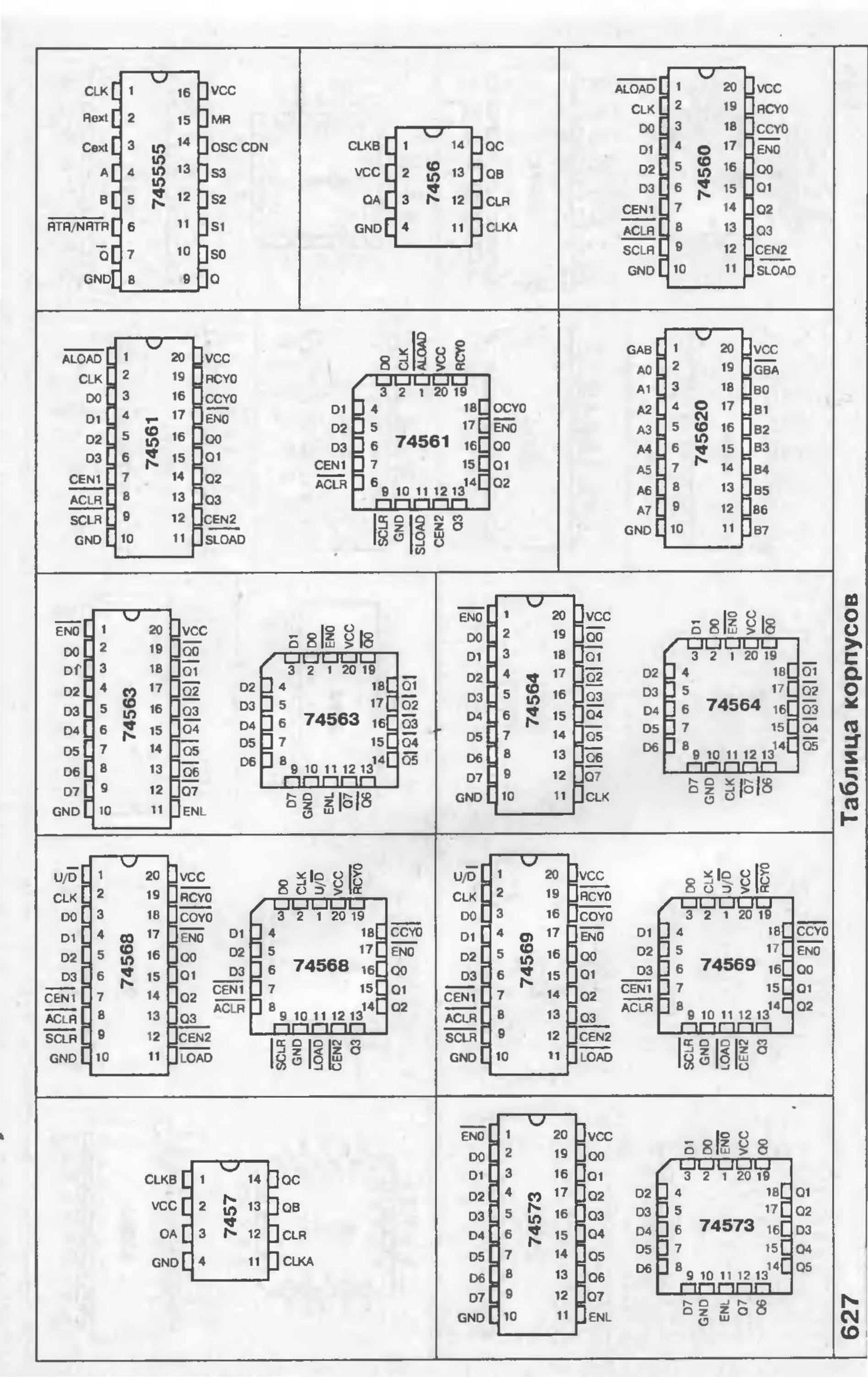
7453/3

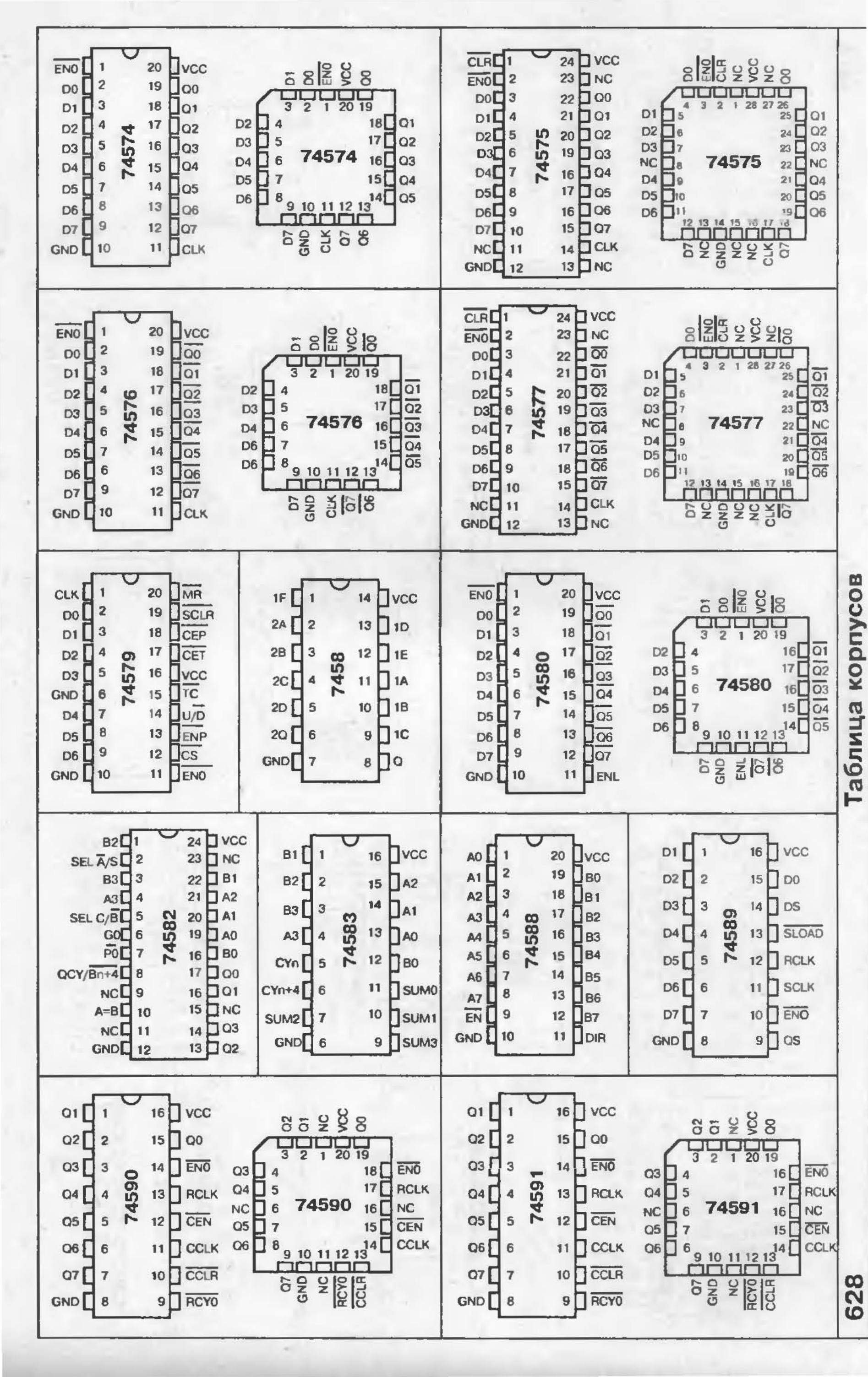
B	1	14	VCC
C	2	13	A
D	3	12	$\overline{X}$
E	4	11	X
F	5	10	I
G	6	9	H
GND	7	8	$\overline{Q}$

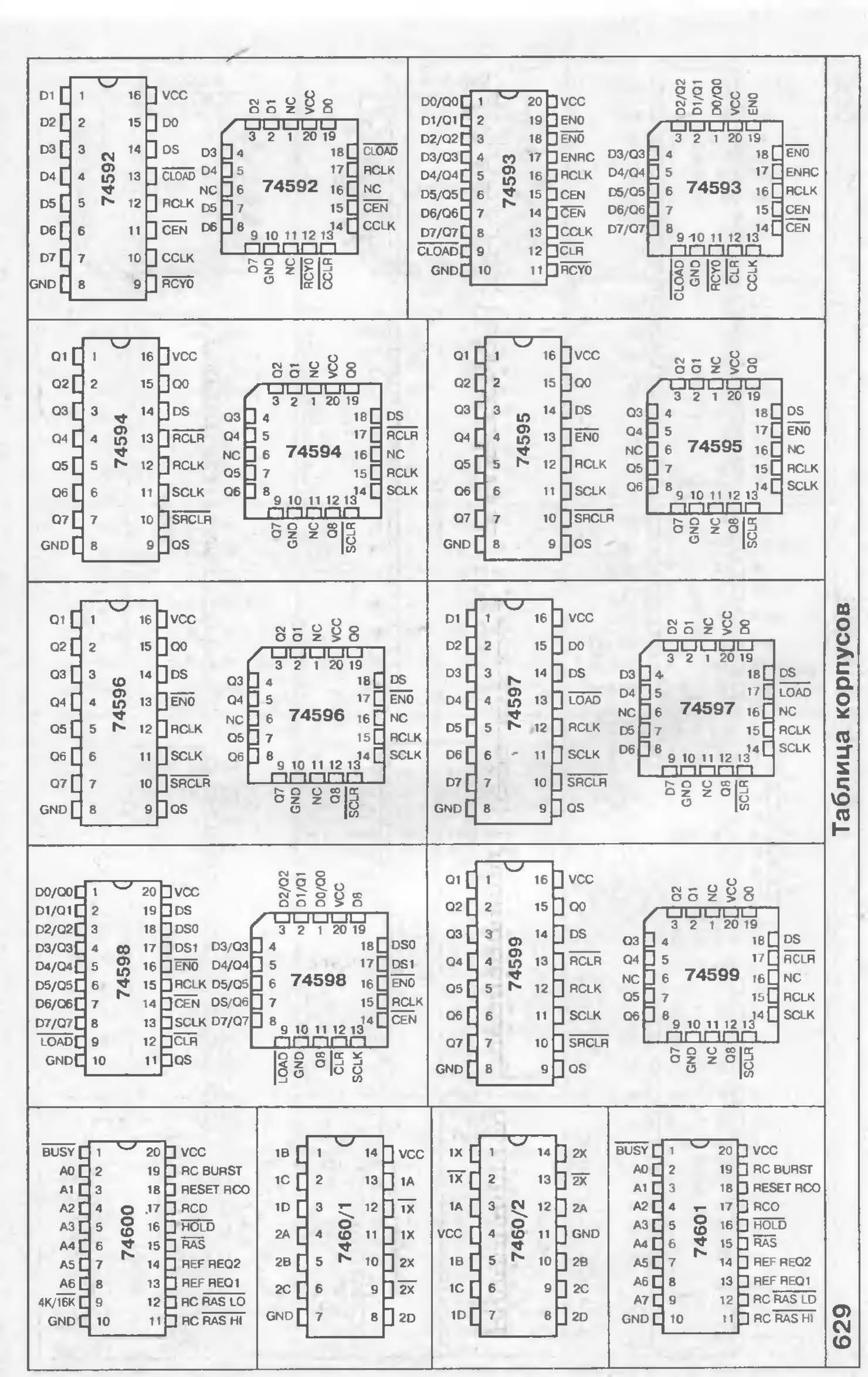

7453/4
745300
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7454/1
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7454/2
7454/3
7454/4
7454/5
7454-6
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74540
7454-5

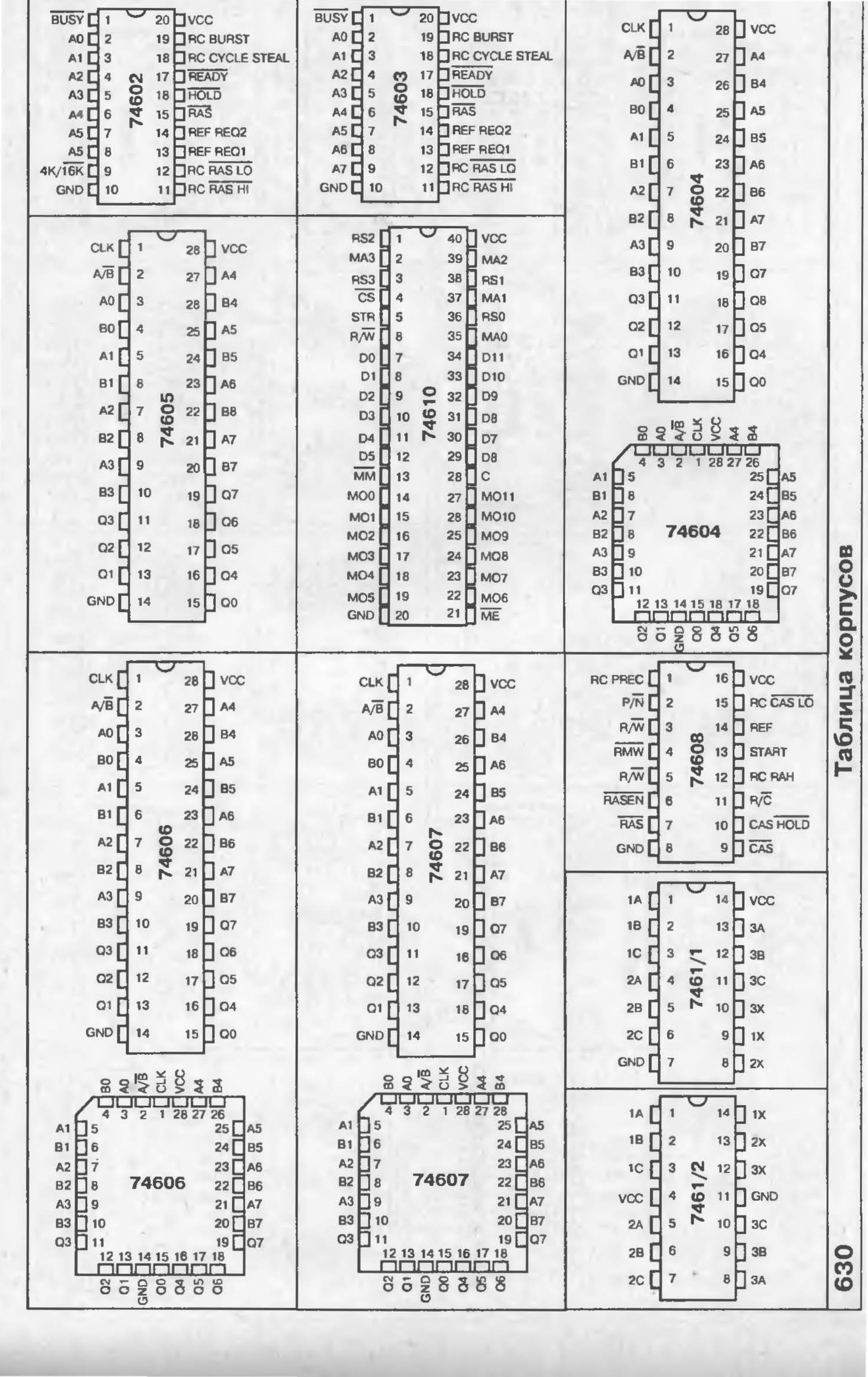


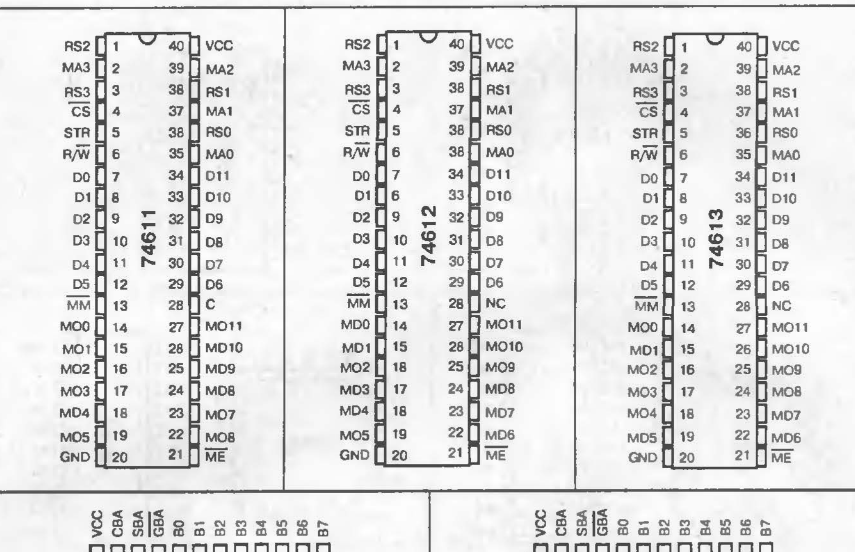
74541
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74545
74547
74548
7455/1
7455/2
7455/3
7455/4
74550
74551
74552
Connections:
PAR parity bit output/input
CER R register clock enable
CPR R register clock
OEBR B port and parity output enable and clear FLB input
OEAS A port output enable and clear FLA input
ERR parity check output
CES S register clock enable
CPS S register clock
FLA flag output port A
FLB flag output port B

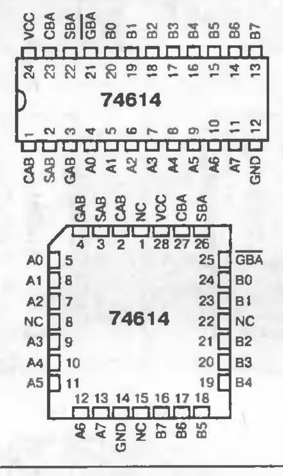

74555
CLK 1, Rext 2, Cext 3, A 4, B 5, RTA/NRTR 6, Q 7, GND 8
VCC 16, MR 15, OSC CDN 14, S3 13, S2 12, S1 11, S0 10, Q 9
7456
CLKB 1, VCC 2, QA 3, GND 4
QC 14, QB 13, CLR 12, CLKA 11
74560
ALOAD 1, CLK 2, D0 3, D1 4, D2 5, D3 6, CEN1 7, ACLR 8, SCLR 9, GND 10
VCC 20, RCY0 19, CCY0 18, EN0 17, Q0 16, Q1 15, Q2 14, Q3 13, CEN2 12, SLOAD 11
74561
ALOAD 1, CLK 2, D0 3, D1 4, D2 5, D3 6, CEN1 7, ACLR 8, SCLR 9, GND 10
VCC 20, RCY0 19, CCY0 16, EN0 17, Q0 16, Q1 15, Q2 14, Q3 13, CEN2 12, SLOAD 11
74561
D0 3, CLK 2, ALOAD 1, VCC 20, RCY0 19
D1 4, D2 5, D3 6, CEN1 7, ACLR 6
OCY0 18, EN0 17, Q0 16, Q1 15, Q2 14
SCLR 9, GND 10, SLOAD 11, CEN2 12, Q3 13
745620
GAB 1, A0 2, A1 3, A2 4, A3 5, A4 6, A5 7, A6 8, A7 9, GND 10
VCC 20, GBA 19, B0 18, B1 17, B2 16, B3 15, B4 14, B5 13, B6 12, B7 11
74563
EN0 1, D0 2, D1 3, D2 4, D3 5, D4 6, D5 7, D6 8, D7 9, GND 10
VCC 20, Q0 19, Q1 18, Q2 17, Q3 16, Q4 15, Q5 14, Q6 13, Q7 12, ENL 11
74563
D1 3, D0 2, EN0 1, VCC 20, Q0 19
D2 4, D3 5, D4 6, D5 7, D6 8
Q1 18, Q2 17, Q3 16, Q4 15, Q5 14
D7 9, GND 10, ENL 11, Q7 12, Q6 13
74564
EN0 1, D0 2, D1 3, D2 4, D3 5, D4 6, D5 7, D6 8, D7 9, GND 10
VCC 20, Q0 19, Q1 18, Q2 17, Q3 16, Q4 15, Q5 14, Q6 13, Q7 12, CLK 11
74564
D1 3, D0 2, EN0 1, VCC 20, Q0 19
D2 4, D3 5, D4 6, D5 7, D6 8
Q1 18, Q2 17, Q3 16, Q4 15, Q5 14
D7 9, GND 10, CLK 11, Q7 12, Q6 13
74568
U/D 1, CLK 2, D0 3, D1 4, D2 5, D3 6, CEN1 7, ACLR 8, SCLR 9, GND 10
VCC 20, RCY0 19, COY0 18, EN0 17, Q0 16, Q1 15, Q2 14, Q3 13, CEN2 12, LOAD 11
74568
D0 3, CLK 2, U/D 1, VCC 20, RCY0 19
D1 4, D2 5, D3 6, CEN1 7, ACLR 8
CCY0 18, EN0 17, Q0 16, Q1 15, Q2 14
SCLR 9, GND 10, LOAD 11, CEN2 12, Q3 13
74569
U/D 1, CLK 2, D0 3, D1 4, D2 5, D3 6, CEN1 7, ACLR 8, SCLR 9, GND 10
VCC 20, RCY0 19, COY0 16, EN0 17, Q0 16, Q1 15, Q2 14, Q3 13, CEN2 12, LOAD 11
74569
D0 3, CLK 2, U/D 1, VCC 20, RCY0 19
D1 4, D2 5, D3 6, CEN1 7, ACLR 8
CCY0 18, EN0 17, Q0 16, Q1 15, Q2 14
SCLR 9, GND 10, LOAD 11, CEN2 12, Q3 13
7457
CLKB 1, VCC 2, OA 3, GND 4
QC 14, QB 13, CLR 12, CLKA 11
74573
EN0 1, D0 2, D1 3, D2 4, D3 5, D4 6, D5 7, D6 8, D7 9, GND 10
VCC 20, Q0 19, Q1 16, Q2 17, Q3 16, Q4 15, Q5 14, Q6 13, Q7 12, ENL 11
74573
D1 3, D0 2, EN0 1, VCC 20, Q0 19
D2 4, D3 5, D4 6, D5 7, D6 8
Q1 18, Q2 17, D3 16, Q4 15, Q5 14
D7 9, GND 10, ENL 11, Q7 12, Q6 13

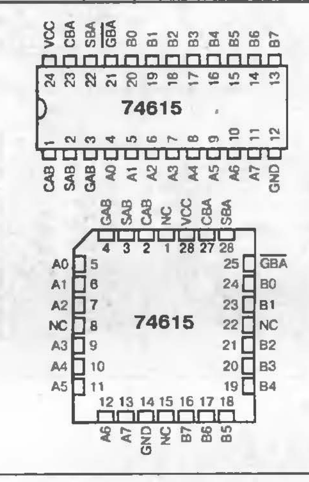

74574
1 EN0, 2 D0, 3 D1, 4 D2, 5 D3, 6 D4, 7 D5, 8 D6, 9 D7, 10 GND
20 VCC, 19 Q0, 18 Q1, 17 Q2, 16 Q3, 15 Q4, 14 Q5, 13 Q6, 12 Q7, 11 CLK
74574
D1 3, D0 2, EN0 1, VCC 20, Q0 19
D2 4, D3 5, D4 6, D5 7, D6 8
18 Q1, 17 Q2, 16 Q3, 15 Q4, 14 Q5
D7 9, GND 10, CLK 11, Q7 12, Q6 13
74575
1 CLR, 2 EN0, 3 D0, 4 D1, 5 D2, 6 D3, 7 D4, 8 D5, 9 D6, 10 D7, 11 NC, 12 GND
24 VCC, 23 NC, 22 Q0, 21 Q1, 20 Q2, 19 Q3, 16 Q4, 17 Q5, 16 Q6, 15 Q7, 14 CLK, 13 NC
74575
D0 4, EN0 3, CLR 2, NC 1, VCC 28, NC 27, Q0 26
D1 5, D2 6, D3 7, NC 8, D4 9, D5 10, D6 11
25 Q1, 24 Q2, 23 Q3, 22 NC, 21 Q4, 20 Q5, 19 Q6
D7 12, NC 13, GND 14, NC 15, NC 16, CLK 17, Q7 18
74576
1 EN0, 2 D0, 3 D1, 4 D2, 5 D3, 6 D4, 7 D5, 6 D6, 9 D7, 10 GND
20 VCC, 19 Q0, 18 Q1, 17 Q2, 16 Q3, 15 Q4, 14 Q5, 13 Q6, 12 Q7, 11 CLK
74576
D1 3, D0 2, EN0 1, VCC 20, Q0 19
D2 4, D3 5, D4 6, D6 7, D6 8
18 Q1, 17 Q2, 16 Q3, 15 Q4, 14 Q5
D7 9, GND 10, CLK 11, Q7 12, Q6 13
74577
1 CLR, 2 EN0, 3 D0, 4 D1, 5 D2, 6 D3, 7 D4, 8 D5, 9 D6, 10 D7, 11 NC, 12 GND
24 VCC, 23 NC, 22 Q0, 21 Q1, 20 Q2, 19 Q3, 18 Q4, 17 Q5, 18 Q6, 15 Q7, 14 CLK, 13 NC
74577
D0 4, EN0 3, CLR 2, NC 1, VCC 28, NC 27, Q0 26
D1 5, D2 6, D3 7, NC 8, D4 9, D5 10, D6 11
25 Q1, 24 Q2, 23 Q3, 22 NC, 21 Q4, 20 Q5, 19 Q6
D7 12, NC 13, GND 14, NC 15, NC 16, CLK 17, Q7 18
74579
1 CLK, 2 D0, 3 D1, 4 D2, 5 D3, 6 GND, 7 D4, 8 D5, 9 D6, 10 GND
20 MR, 19 SCLR, 18 CEP, 17 CET, 16 VCC, 15 TC, 14 U/D, 13 ENP, 12 CS, 11 EN0
7458
1 1F, 2 2A, 3 2B, 4 2C, 5 2D, 6 2Q, 7 GND
14 VCC, 13 1D, 12 1E, 11 1A, 10 1B, 9 1C, 8 Q
74580
1 EN0, 2 D0, 3 D1, 4 D2, 5 D3, 6 D4, 7 D5, 8 D6, 9 D7, 10 GND
20 VCC, 19 Q0, 18 Q1, 17 Q2, 16 Q3, 15 Q4, 14 Q5, 13 Q6, 12 Q7, 11 ENL
74580
D1 3, D0 2, EN0 1, VCC 20, Q0 19
D2 4, D3 5, D4 6, D5 7, D6 8
16 Q1, 17 Q2, 16 Q3, 15 Q4, 14 Q5
D7 9, GND 10, ENL 11, Q7 12, Q6 13
74582
1 B2, 2 SEL A/S, 3 B3, 4 A3, 5 SEL C/B, 6 G0, 7 P0, 8 QCY/Bn+4, 9 NC, 10 A=B, 11 NC, 12 GND
24 VCC, 23 NC, 22 B1, 21 A2, 20 A1, 19 A0, 16 B0, 17 Q0, 16 Q1, 15 NC, 14 Q3, 13 Q2
74583
1 B1, 2 B2, 3 B3, 4 A3, 5 CYn, 6 CYn+4, 7 SUM2, 6 GND
16 VCC, 15 A2, 14 A1, 13 A0, 12 B0, 11 SUM0, 10 SUM1, 9 SUM3
74588
1 A0, 2 A1, 3 A2, 4 A3, 5 A4, 6 A5, 7 A6, 8 A7, 9 EN, 10 GND
20 VCC, 19 B0, 18 B1, 17 B2, 16 B3, 15 B4, 14 B5, 13 B6, 12 B7, 11 DIR
74589
1 D1, 2 D2, 3 D3, 4 D4, 5 D5, 6 D6, 7 D7, 8 GND
16 VCC, 15 D0, 14 DS, 13 SLOAD, 12 RCLK, 11 SCLK, 10 EN0, 9 QS
74590
1 Q1, 2 Q2, 3 Q3, 4 Q4, 5 Q5, 6 Q6, 7 Q7, 8 GND
16 VCC, 15 Q0, 14 EN0, 13 RCLK, 12 CEN, 11 CCLK, 10 CCLR, 9 RCY0
74590
Q2 3, Q1 2, NC 1, VCC 20, Q0 19
Q3 4, Q4 5, NC 6, Q5 7, Q6 8
18 EN0, 17 RCLK, 16 NC, 15 CEN, 14 CCLK
Q7 9, GND 10, NC 11, RCY0 12, CCLR 13
74591
1 Q1, 2 Q2, 3 Q3, 4 Q4, 5 Q5, 6 Q6, 7 Q7, 8 GND
16 VCC, 15 Q0, 14 EN0, 13 RCLK, 12 CEN, 11 CCLK, 10 CCLR, 9 RCY0
74591
Q2 3, Q1 2, NC 1, VCC 20, Q0 19
Q3 4, Q4 5, NC 6, Q5 7, Q6 6
16 EN0, 17 RCLK, 16 NC, 15 CEN, 14 CCLK
Q7 9, GND 10, NC 11, RCY0 12, CCLR 13

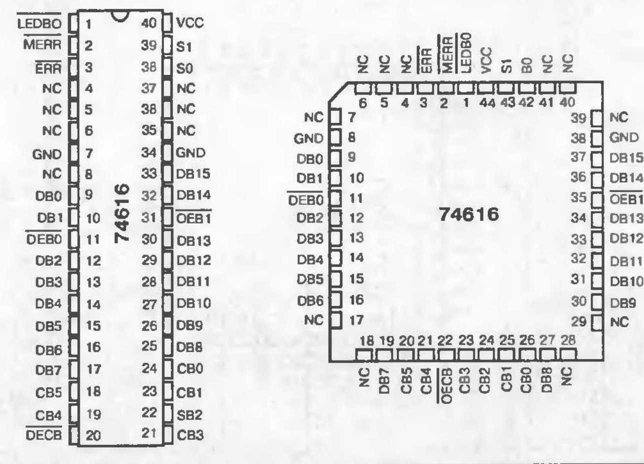

74592
D1 1 · 16 VCC
D2 2 · 15 D0
D3 3 · 14 DS
D4 4 · 13 CLOAD
D5 5 · 12 RCLK
D6 6 · 11 CEN
D7 7 · 10 CCLK
GND 8 · 9 RCY0
74592
D2 3, D1 2, NC 1, VCC 20, D0 19
D3 4, D4 5, NC 6, D5 7, D6 8
18 CLOAD, 17 RCLK, 16 NC, 15 CEN, 14 CCLK
D7 9, GND 10, NC 11, RCY0 12, CCLR 13
74593
D0/Q0 1 · 20 VCC
D1/Q1 2 · 19 EN0
D2/Q2 3 · 18 EN0
D3/Q3 4 · 17 ENRC
D4/Q4 5 · 16 RCLK
D5/Q5 6 · 15 CEN
D6/Q6 7 · 14 CEN
D7/Q7 8 · 13 CCLK
CLOAD 9 · 12 CLR
GND 10 · 11 RCY0
74593
D2/Q2 3, D1/Q1 2, D0/Q0 1, VCC 20, EN0 19
D3/Q3 4, D4/Q4 5, D5/Q5 6, D6/Q6 7, D7/Q7 8
18 EN0, 17 ENRC, 16 RCLK, 15 CEN, 14 CEN
CLOAD 9, GND 10, RCY0 11, CLR 12, CCLK 13
74594
Q1 1 · 16 VCC
Q2 2 · 15 Q0
Q3 3 · 14 DS
Q4 4 · 13 RCLR
Q5 5 · 12 RCLK
Q6 6 · 11 SCLK
Q7 7 · 10 SRCLR
GND 8 · 9 QS
74594
Q2 3, Q1 2, NC 1, VCC 20, Q0 19
Q3 4, Q4 5, NC 6, Q5 7, Q6 8
18 DS, 17 RCLR, 16 NC, 15 RCLK, 14 SCLK
Q7 9, GND 10, NC 11, Q8 12, SCLR 13
74595
Q1 1 · 16 VCC
Q2 2 · 15 Q0
Q3 3 · 14 DS
Q4 4 · 13 EN0
Q5 5 · 12 RCLK
Q6 6 · 11 SCLK
Q7 7 · 10 SRCLR
GND 8 · 9 QS
74595
Q2 3, Q1 2, NC 1, VCC 20, Q0 19
Q3 4, Q4 5, NC 6, Q5 7, Q6 8
18 DS, 17 EN0, 16 NC, 15 RCLK, 14 SCLK
Q7 9, GND 10, NC 11, Q8 12, SCLR 13
74596
Q1 1 · 16 VCC
Q2 2 · 15 Q0
Q3 3 · 14 DS
Q4 4 · 13 EN0
Q5 5 · 12 RCLK
Q6 6 · 11 SCLK
Q7 7 · 10 SRCLR
GND 8 · 9 QS
74596
Q2 3, Q1 2, NC 1, VCC 20, Q0 19
Q3 4, Q4 5, NC 6, Q5 7, Q6 8
18 DS, 17 EN0, 16 NC, 15 RCLK, 14 SCLK
Q7 9, GND 10, NC 11, Q8 12, SCLR 13
74597
D1 1 · 16 VCC
D2 2 · 15 D0
D3 3 · 14 DS
D4 4 · 13 LOAD
D5 5 · 12 RCLK
D6 6 · 11 SCLK
D7 7 · 10 SRCLR
GND 8 · 9 QS
74597
D2 3, D1 2, NC 1, VCC 20, D0 19
D3 4, D4 5, NC 6, D5 7, D6 8
18 DS, 17 LOAD, 16 NC, 15 RCLK, 14 SCLK
D7 9, GND 10, NC 11, Q8 12, SCLR 13
74598
D0/Q0 1 · 20 VCC
D1/Q1 2 · 19 DS
D2/Q2 3 · 18 DS0
D3/Q3 4 · 17 DS1
D4/Q4 5 · 16 EN0
D5/Q5 6 · 15 RCLK
D6/Q6 7 · 14 CEN
D7/Q7 8 · 13 SCLK
LOAD 9 · 12 CLR
GND 10 · 11 QS
74598
D2/Q2 3, D1/Q1 2, D0/Q0 1, VCC 20, D8 19
D3/Q3 4, D4/Q4 5, D5/Q5 6, DS/Q6 7, D7/Q7 8
18 DS0, 17 DS1, 16 EN0, 15 RCLK, 14 CEN
LOAD 9, GND 10, Q8 11, CLR 12, SCLK 13
74599
Q1 1 · 16 VCC
Q2 2 · 15 Q0
Q3 3 · 14 DS
Q4 4 · 13 RCLR
Q5 5 · 12 RCLK
Q6 6 · 11 SCLK
Q7 7 · 10 SRCLR
GND 8 · 9 QS
74599
Q2 3, Q1 2, NC 1, VCC 20, Q0 19
Q3 4, Q4 5, NC 6, Q5 7, Q6 8
18 DS, 17 RCLR, 16 NC, 15 RCLK, 14 SCLK
Q7 9, GND 10, NC 11, Q8 12, SCLR 13
74600
BUSY 1 · 20 VCC
A0 2 · 19 RC BURST
A1 3 · 18 RESET RCO
A2 4 · 17 RCD
A3 5 · 16 HOLD
A4 6 · 15 RAS
A5 7 · 14 REF REQ2
A6 8 · 13 REF REQ1
4K/16K 9 · 12 RC RAS LO
GND 10 · 11 RC RAS HI
7460/1
1B 1 · 14 VCC
1C 2 · 13 1A
1D 3 · 12 1X
2A 4 · 11 1X
2B 5 · 10 2X
2C 6 · 9 2X
GND 7 · 8 2D
7460/2
1X 1 · 14 2X
1X 2 · 13 2X
1A 3 · 12 2A
VCC 4 · 11 GND
1B 5 · 10 2B
1C 6 · 9 2C
1D 7 · 8 2D
74601
BUSY 1 · 20 VCC
A0 2 · 19 RC BURST
A1 3 · 18 RESET RCO
A2 4 · 17 RCO
A3 5 · 16 HOLD
A4 6 · 15 RAS
A5 7 · 14 REF REQ2
A6 8 · 13 REF REQ1
A7 9 · 12 RC RAS LD
GND 10 · 11 RC RAS HI

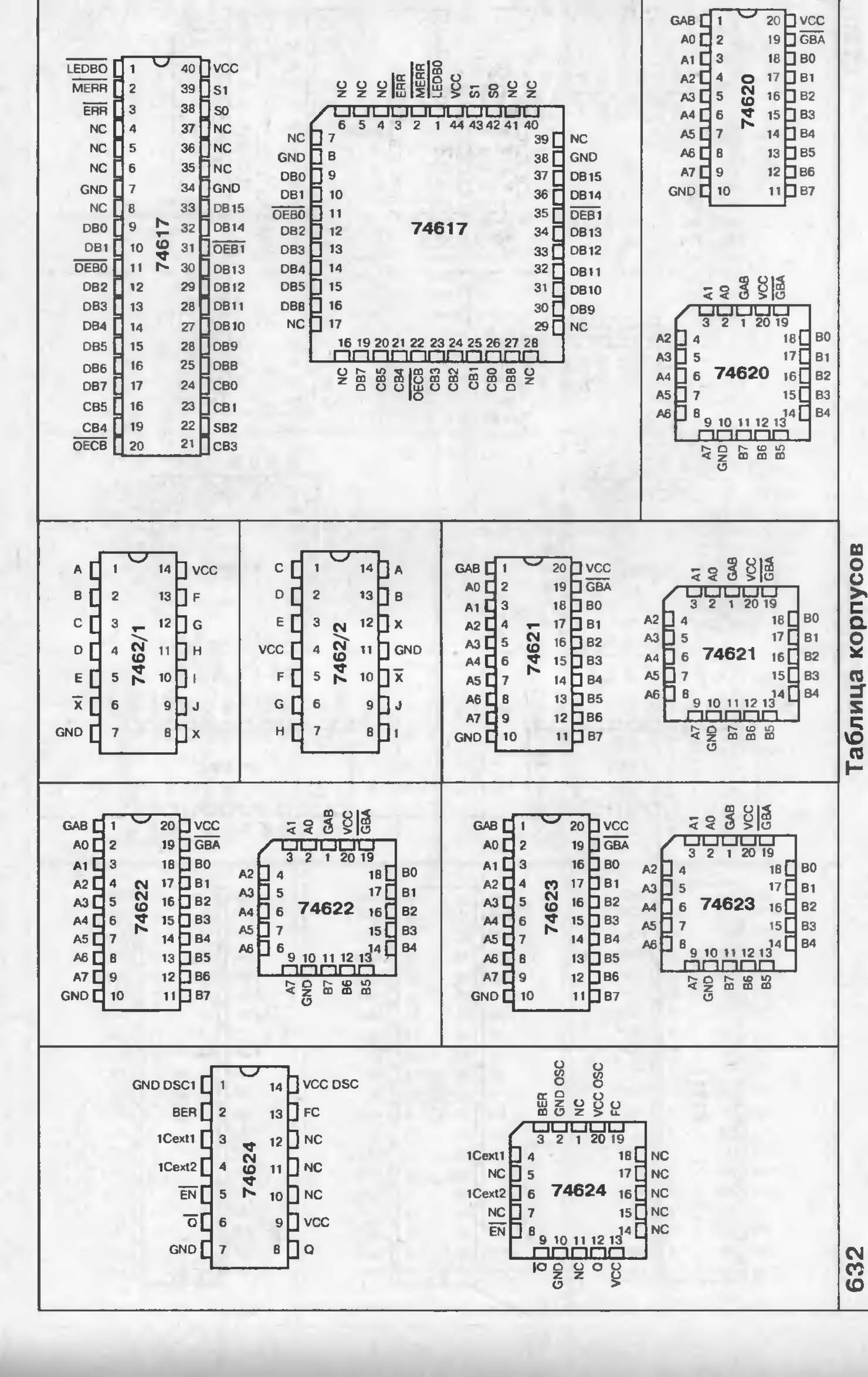

74602
BUSY 1, A0 2, A1 3, A2 4, A3 5, A4 6, A5 7, A5 8, 4K/16K 9, GND 10
20 VCC, 19 RC BURST, 18 RC CYCLE STEAL, 17 READY, 18 HOLD, 15 RAS, 14 REF REQ2, 13 REF REQ1, 12 RC RAS LO, 11 RC RAS HI
74603
BUSY 1, A0 2, A1 3, A2 4, A3 5, A4 6, A5 7, A6 8, A7 9, GND 10
20 VCC, 19 RC BURST, 18 RC CYCLE STEAL, 17 READY, 18 HOLD, 15 RAS, 14 REF REQ2, 13 REF REQ1, 12 RC RAS LO, 11 RC RAS HI
74604
CLK 1, A/B 2, A0 3, B0 4, A1 5, B1 6, A2 7, B2 8, A3 9, B3 10, Q3 11, Q2 12, Q1 13, GND 14
28 VCC, 27 A4, 26 B4, 25 A5, 24 B5, 23 A6, 22 B6, 21 A7, 20 B7, 19 Q7, 18 Q8, 17 Q5, 16 Q4, 15 Q0
74605
CLK 1, A/B 2, A0 3, B0 4, A1 5, B1 6, A2 7, B2 8, A3 9, B3 10, Q3 11, Q2 12, Q1 13, GND 14
28 VCC, 27 A4, 28 B4, 25 A5, 24 B5, 23 A6, 22 B8, 21 A7, 20 B7, 19 Q7, 18 Q6, 17 Q5, 16 Q4, 15 Q0
74610
RS2 1, MA3 2, RS3 3, CS 4, STR 5, R/W 8, D0 7, D1 8, D2 9, D3 10, D4 11, D5 12, MM 13, MO0 14, MO1 15, MO2 16, MO3 17, MO4 18, MO5 19, GND 20
40 VCC, 39 MA2, 38 RS1, 37 MA1, 36 RS0, 35 MA0, 34 D11, 33 D10, 32 D9, 31 D8, 30 D7, 29 D8, 28 C, 27 MO11, 28 MO10, 25 MO9, 24 MO8, 23 MO7, 22 MO6, 21 ME
74604
B0 4, A0 3, A/B 2, CLK 1, VCC 28, A4 27, B4 26
A1 5, B1 8, A2 7, B2 8, A3 9, B3 10, Q3 11
25 A5, 24 B5, 23 A6, 22 B6, 21 A7, 20 B7, 19 Q7
12 Q2, 13 Q1, 14 GND, 15 Q0, 18 Q4, 17 Q5, 18 Q6
74606
CLK 1, A/B 2, A0 3, B0 4, A1 5, B1 6, A2 7, B2 8, A3 9, B3 10, Q3 11, Q2 12, Q1 13, GND 14
28 VCC, 27 A4, 28 B4, 25 A5, 24 B5, 23 A6, 22 B6, 21 A7, 20 B7, 19 Q7, 18 Q6, 17 Q5, 16 Q4, 15 Q0
74607
CLK 1, A/B 2, A0 3, B0 4, A1 5, B1 6, A2 7, B2 8, A3 9, B3 10, Q3 11, Q2 12, Q1 13, GND 14
28 VCC, 27 A4, 26 B4, 25 A6, 24 B5, 23 A6, 22 B6, 21 A7, 20 B7, 19 Q7, 16 Q6, 17 Q5, 18 Q4, 15 Q0
74608
RC PREC 1, P/N 2, R/W 3, RMW 4, R/W 5, RASEN 6, RAS 7, GND 8
16 VCC, 15 RC CAS LO, 14 REF, 13 START, 12 RC RAH, 11 R/C, 10 CAS HOLD, 9 CAS
74606
B0 4, A0 3, A/B 2, CLK 1, VCC 28, A4 27, B4 26
A1 5, B1 6, A2 7, B2 8, A3 9, B3 10, Q3 11
25 A5, 24 B5, 23 A6, 22 B6, 21 A7, 20 B7, 19 Q7
12 Q2, 13 Q1, 14 GND, 15 Q0, 16 Q4, 17 Q5, 18 Q6
74607
B0 4, A0 3, A/B 2, CLK 1, VCC 28, A4 27, B4 28
A1 5, B1 6, A2 7, B2 8, A3 9, B3 10, Q3 11
25 A5, 24 B5, 23 A6, 22 B6, 21 A7, 20 B7, 19 Q7
12 Q2, 13 Q1, 14 GND, 15 Q0, 16 Q4, 17 Q5, 18 Q6
7461/1
1A 1, 1B 2, 1C 3, 2A 4, 2B 5, 2C 6, GND 7
14 VCC, 13 3A, 12 3B, 11 3C, 10 3X, 9 1X, 8 2X
7461/2
1A 1, 1B 2, 1C 3, VCC 4, 2A 5, 2B 6, 2C 7
14 1X, 13 2X, 12 3X, 11 GND, 10 3C, 9 3B, 8 3A

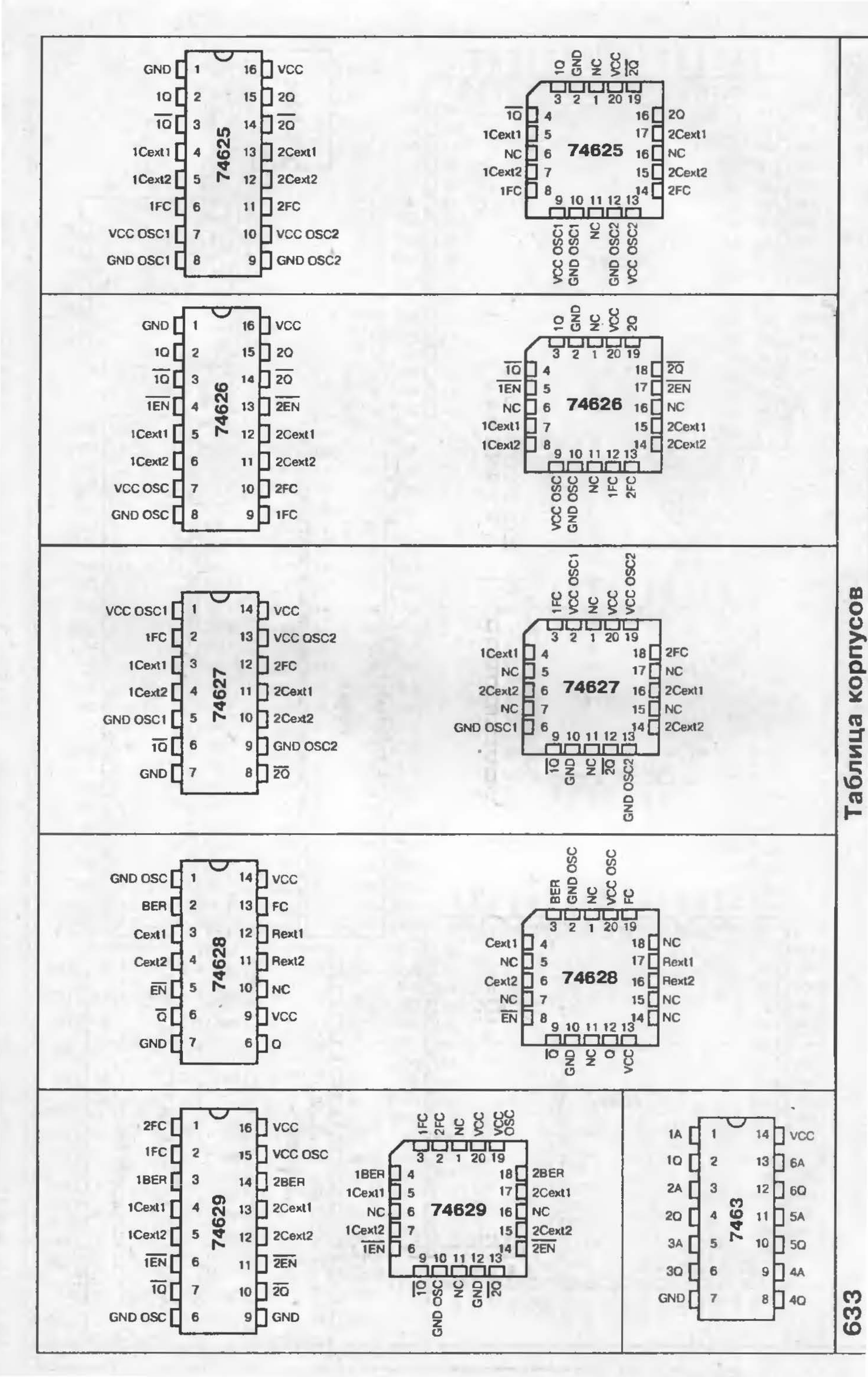

74611
RS2 1 40 VCC
MA3 2 39 MA2
RS3 3 38 RS1
CS 4 37 MA1
STR 5 38 RS0
R/W 6 35 MA0
D0 7 34 D11
D1 8 33 D10
D2 9 32 D9
D3 10 31 D8
D4 11 30 D7
D5 12 29 D6
MM 13 28 C
MO0 14 27 MO11
MO1 15 28 MD10
MO2 16 25 MD9
MO3 17 24 MD8
MD4 18 23 MO7
MO5 19 22 MO8
GND 20 21 ME
74612
RS2 1 40 VCC
MA3 2 39 MA2
RS3 3 38 RS1
CS 4 37 MA1
STR 5 38 RS0
R/W 6 38 MA0
D0 7 34 D11
D1 6 33 D10
D2 9 32 D9
D3 10 31 D8
D4 11 30 D7
D5 12 29 D6
MM 13 28 NC
MD0 14 27 MO11
MD1 15 28 MO10
MO2 18 25 MO9
MD3 17 24 MD8
MD4 18 23 MD7
MO5 19 22 MD6
GND 20 21 ME
74613
RS2 1 40 VCC
MA3 2 39 MA2
RS3 3 38 RS1
CS 4 37 MA1
STR 5 36 RS0
R/W 6 35 MA0
D0 7 34 D11
D1 8 33 D10
D2 9 32 D9
D3 10 31 D8
D4 11 30 D7
D5 12 29 D6
MM 13 28 NC
MO0 14 27 MO11
MD1 15 26 MO10
MO2 16 25 MO9
MO3 17 24 MO8
MO4 18 23 MD7
MD5 19 22 MD6
GND 20 21 ME

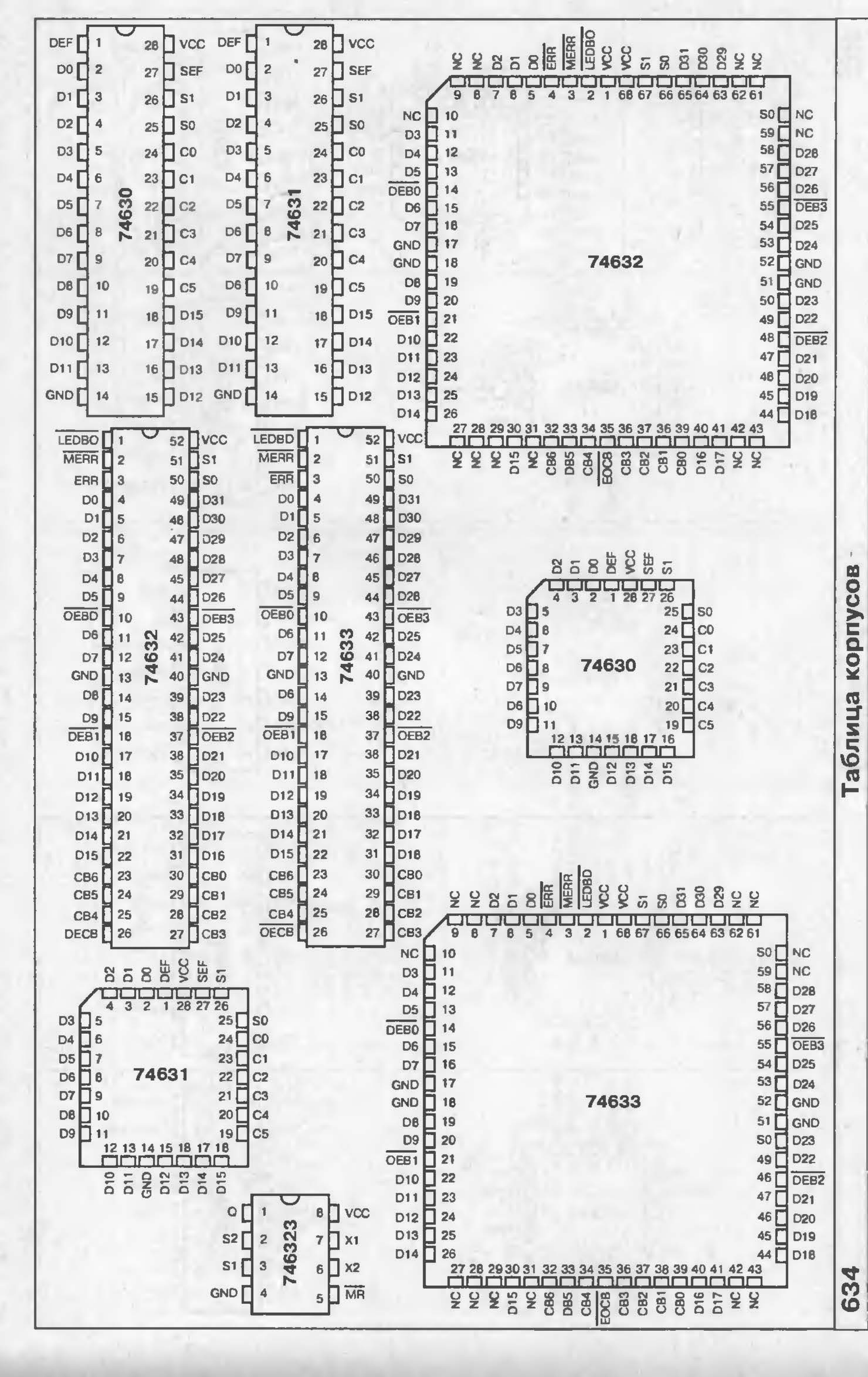

74614
VCC 24, CBA 23, SBA 22, GBA 21, B0 20, B1 19, B2 18, B3 17, B4 16, B5 15, B6 14, B7 13
CAB 1, SAB 2, GAB 3, A0 4, A1 5, A2 6, A3 7, A4 8, A5 9, A6 10, A7 11, GND 12
74614
GAB 4, SAB 3, CAB 2, NC 1, VCC 28, CBA 27, SBA 26
A0 5, A1 8, A2 7, NC 8, A3 9, A4 10, A5 11
25 GBA, 24 B0, 23 B1, 22 NC, 21 B2, 20 B3, 19 B4
12 A6, 13 A7, 14 GND, 15 NC, 16 B7, 17 B6, 18 B5


74615
VCC 24, CBA 23, SBA 22, GBA 21, B0 20, B1 19, B2 18, B3 17, B4 16, B5 15, B6 14, B7 13
CAB 1, SAB 2, GAB 3, A0 4, A1 5, A2 6, A3 7, A4 8, A5 9, A6 10, A7 11, GND 12
74615
GAB 4, SAB 3, CAB 2, NC 1, VCC 28, CBA 27, SBA 28
A0 5, A1 6, A2 7, NC 8, A3 9, A4 10, A5 11
25 GBA, 24 B0, 23 B1, 22 NC, 21 B2, 20 B3, 19 B4
12 A6, 13 A7, 14 GND, 15 NC, 16 B7, 17 B6, 18 B5


74616
LEDBO 1 40 VCC
MERR 2 39 S1
ERR 3 38 S0
NC 4 37 NC
NC 5 38 NC
NC 6 35 NC
GND 7 34 GND
NC 8 33 DB15
DB0 9 32 DB14
DB1 10 31 OEB1
DEB0 11 30 DB13
DB2 12 29 DB12
DB3 13 28 DB11
DB4 14 27 DB10
DB5 15 26 DB9
DB6 16 25 DB8
DB7 17 24 CB0
CB5 18 23 CB1
CB4 19 22 SB2
DECB 20 21 CB3
74616
NC 6, NC 5, NC 4, ERR 3, MERR 2, LEDB0 1, VCC 44, S1 43, B0 42, NC 41, NC 40
NC 7, GND 8, DB0 9, DB1 10, DEB0 11, DB2 12, DB3 13, DB4 14, DB5 15, DB6 16, NC 17
39 NC, 38 GND, 37 DB15, 36 DB14, 35 OEB1, 34 DB13, 33 DB12, 32 DB11, 31 DB10, 30 DB9, 29 NC
18 NC, 19 DB7, 20 CB5, 21 CB4, 22 OECB, 23 CB3, 24 CB2, 25 CB1, 26 CB0, 27 DB8, 28 NC


74617
LEDBO MERR ERR NC NC NC GND NC DB0 DB1 DEB0 DB2 DB3 DB4 DB5 DB6 DB7 CB5 CB4 OECB
VCC S1 S0 NC NC NC GND DB15 DB14 OEB1 DB13 DB12 DB11 DB10 DB9 DBB CB0 CB1 SB2 CB3
74617
NC NC NC ERR MERR LEDB0 VCC S1 S0 NC NC
NC GND DB0 DB1 OEB0 DB2 DB3 DB4 DB5 DB6 NC
NC GND DB15 DB14 DEB1 DB13 DB12 DB11 DB10 DB9 NC
NC DB7 CB5 CB4 OECB CB3 CB2 CB1 CB0 DB8 NC
74620
GAB A0 A1 A2 A3 A4 A5 A6 A7 GND
VCC GBA B0 B1 B2 B3 B4 B5 B6 B7
74620
A1 A0 GAB VCC GBA
A2 A3 A4 A5 A6
B0 B1 B2 B3 B4
A7 GND B7 B6 B5
7462/1
A B C D E X GND
VCC F G H I J X
7462/2
C D E VCC F G H
A B X GND X J I
74621
GAB A0 A1 A2 A3 A4 A5 A6 A7 GND
VCC GBA B0 B1 B2 B3 B4 B5 B6 B7
74621
A1 A0 GAB VCC GBA
A2 A3 A4 A5 A6
B0 B1 B2 B3 B4
A7 GND B7 B6 B5
74622
GAB A0 A1 A2 A3 A4 A5 A6 A7 GND
VCC GBA B0 B1 B2 B3 B4 B5 B6 B7
74622
A1 A0 GAB VCC GBA
A2 A3 A4 A5 A6
B0 B1 B2 B3 B4
A7 GND B7 B6 B5
74623
GAB A0 A1 A2 A3 A4 A5 A6 A7 GND
VCC GBA B0 B1 B2 B3 B4 B5 B6 B7
74623
A1 A0 GAB VCC GBA
A2 A3 A4 A5 A6
B0 B1 B2 B3 B4
A7 GND B7 B6 B5
74624
GND DSC1 BER 1Cext1 1Cext2 EN Q GND
VCC DSC FC NC NC NC VCC Q
74624
BER GND OSC NC VCC OSC FC
1Cext1 NC 1Cext2 NC EN
NC NC NC NC NC
Q GND NC Q VCC


74625
GND 1 16 VCC
1Q 2 15 2Q
1Q̄ 3 14 2Q̄
1Cext1 4 13 2Cext1
1Cext2 5 12 2Cext2
1FC 6 11 2FC
VCC OSC1 7 10 VCC OSC2
GND OSC1 8 9 GND OSC2
74625
1Q GND NC VCC 2Q̄
3 2 1 20 19
1Q̄ 4 16 2Q
1Cext1 5 17 2Cext1
NC 6 16 NC
1Cext2 7 15 2Cext2
1FC 8 14 2FC
9 10 11 12 13
VCC OSC1 GND OSC1 NC GND OSC2 VCC OSC2
74626
GND 1 16 VCC
1Q 2 15 2Q
1Q̄ 3 14 2Q̄
1EN̄ 4 13 2EN̄
1Cext1 5 12 2Cext1
1Cext2 6 11 2Cext2
VCC OSC 7 10 2FC
GND OSC 8 9 1FC
74626
1Q GND NC VCC 2Q
3 2 1 20 19
1Q̄ 4 18 2Q̄
1EN̄ 5 17 2EN̄
NC 6 16 NC
1Cext1 7 15 2Cext1
1Cext2 8 14 2Cext2
9 10 11 12 13
VCC OSC GND OSC NC 1FC 2FC
74627
VCC OSC1 1 14 VCC
1FC 2 13 VCC OSC2
1Cext1 3 12 2FC
1Cext2 4 11 2Cext1
GND OSC1 5 10 2Cext2
1Q̄ 6 9 GND OSC2
GND 7 8 2Q̄
74627
1FC VCC OSC1 NC VCC VCC OSC2
3 2 1 20 19
1Cext1 4 18 2FC
NC 5 17 NC
2Cext2 6 16 2Cext1
NC 7 15 NC
GND OSC1 6 14 2Cext2
9 10 11 12 13
1Q̄ GND NC 2Q̄ GND OSC2
74628
GND OSC 1 14 VCC
BER 2 13 FC
Cext1 3 12 Rext1
Cext2 4 11 Rext2
EN̄ 5 10 NC
Q̄ 6 9 VCC
GND 7 6 Q
74628
BER GND OSC NC VCC OSC FC
3 2 1 20 19
Cext1 4 18 NC
NC 5 17 Rext1
Cext2 6 16 Rext2
NC 7 15 NC
EN̄ 8 14 NC
9 10 11 12 13
Q̄ GND NC Q VCC
74629
2FC 1 16 VCC
1FC 2 15 VCC OSC
1BER 3 14 2BER
1Cext1 4 13 2Cext1
1Cext2 5 12 2Cext2
1EN̄ 6 11 2EN̄
1Q̄ 7 10 2Q̄
GND OSC 6 9 GND
74629
1FC 2FC NC VCC VCC OSC
3 2 1 20 19
1BER 4 18 2BER
1Cext1 5 17 2Cext1
NC 6 16 NC
1Cext2 7 15 2Cext2
1EN̄ 6 14 2EN̄
9 10 11 12 13
1Q̄ GND OSC NC GND 2Q̄
7463
1A 1 14 VCC
1Q 2 13 6A
2A 3 12 6Q
2Q 4 11 5A
3A 5 10 5Q
3Q 6 9 4A
GND 7 8 4Q


74630
DEF 1 28 VCC
D0 2 27 SEF
D1 3 26 S1
D2 4 25 S0
D3 5 24 C0
D4 6 23 C1
D5 7 22 C2
D6 8 21 C3
D7 9 20 C4
D8 10 19 C5
D9 11 18 D15
D10 12 17 D14
D11 13 16 D13
GND 14 15 D12
74631
DEF 1 28 VCC
D0 2 27 SEF
D1 3 26 S1
D2 4 25 S0
D3 5 24 C0
D4 6 23 C1
D5 7 22 C2
D6 8 21 C3
D7 9 20 C4
D8 10 19 C5
D9 11 18 D15
D10 12 17 D14
D11 13 16 D13
GND 14 15 D12
74632
LEDBO 1 52 VCC
MERR 2 51 S1
ERR 3 50 S0
D0 4 49 D31
D1 5 48 D30
D2 6 47 D29
D3 7 46 D28
D4 8 45 D27
D5 9 44 D26
OEBO 10 43 DEB3
D6 11 42 D25
D7 12 41 D24
GND 13 40 GND
D8 14 39 D23
D9 15 38 D22
DEB1 16 37 OEB2
D10 17 36 D21
D11 18 35 D20
D12 19 34 D19
D13 20 33 D18
D14 21 32 D17
D15 22 31 D16
CB6 23 30 CB0
CB5 24 29 CB1
CB4 25 28 CB2
DECB 26 27 CB3
74633
LEDBD 1 52 VCC
MERR 2 51 S1
ERR 3 50 S0
D0 4 49 D31
D1 5 48 D30
D2 6 47 D29
D3 7 46 D28
D4 8 45 D27
D5 9 44 D26
OEB0 10 43 OEB3
D6 11 42 D25
D7 12 41 D24
GND 13 40 GND
D6 14 39 D23
D9 15 38 D22
OEB1 16 37 OEB2
D10 17 36 D21
D11 18 35 D20
D12 19 34 D19
D13 20 33 D18
D14 21 32 D17
D15 22 31 D16
CB6 23 30 CB0
CB5 24 29 CB1
CB4 25 28 CB2
OECB 26 27 CB3
74632
NC 9, NC 8, D2 7, D1 6, D0 5, ERR 4, MERR 3, LEDBO 2, VCC 1, VCC 68, S1 67, S0 66, D31 65, D30 64, D29 63, NC 62, NC 61
NC 10, D3 11, D4 12, D5 13, DEB0 14, D6 15, D7 16, GND 17, GND 18, D8 19, D9 20, OEB1 21, D10 22, D11 23, D12 24, D13 25, D14 26
NC 27, NC 28, NC 29, D15 30, NC 31, CB6 32, DB5 33, CB4 34, EOCB 35, CB3 36, CB2 37, CB1 36, CB0 39, D16 40, D17 41, NC 42, NC 43
S0 NC, 59 NC, 58 D28, 57 D27, 56 D26, 55 DEB3, 54 D25, 53 D24, 52 GND, 51 GND, 50 D23, 49 D22, 48 DEB2, 47 D21, 46 D20, 45 D19, 44 D18
74630
D2 4, D1 3, D0 2, DEF 1, VCC 28, SEF 27, S1 26
D3 5, D4 6, D5 7, D6 8, D7 9, D6 10, D9 11
25 S0, 24 C0, 23 C1, 22 C2, 21 C3, 20 C4, 19 C5
12 D10, 13 D11, 14 GND, 15 D12, 16 D13, 17 D14, 16 D15
74631
D2 4, D1 3, D0 2, DEF 1, VCC 28, SEF 27, S1 26
D3 5, D4 6, D5 7, D6 8, D7 9, D8 10, D9 11
25 S0, 24 C0, 23 C1, 22 C2, 21 C3, 20 C4, 19 C5
12 D10, 13 D11, 14 GND, 15 D12, 18 D13, 17 D14, 18 D15
74633
NC 9, NC 8, D2 7, D1 6, D0 5, ERR 4, MERR 3, LEDBD 2, VCC 1, VCC 68, S1 67, S0 66, D31 65, D30 64, D29 63, NC 62, NC 61
NC 10, D3 11, D4 12, D5 13, DEB0 14, D6 15, D7 16, GND 17, GND 18, D8 19, D9 20, OEB1 21, D10 22, D11 23, D12 24, D13 25, D14 26
NC 27, NC 28, NC 29, D15 30, NC 31, CB6 32, DB5 33, CB4 34, EOCB 35, CB3 36, CB2 37, CB1 38, CB0 39, D16 40, D17 41, NC 42, NC 43
S0 NC, 59 NC, 58 D28, 57 D27, 56 D26, 55 OEB3, 54 D25, 53 D24, 52 GND, 51 GND, S0 D23, 49 D22, 46 DEB2, 47 D21, 46 D20, 45 D19, 44 D18
746323
Q 1 8 VCC
S2 2 7 X1
S1 3 6 X2
GND 4 5 MR

74634 (DIP-48)

Pin	Signal	Pin	Signal
1	$\overline{MERR}$	48	VCC
2	$\overline{ERR}$	47	S1
3	D0	46	S0
4	D1	45	D31
5	D2	44	D30
6	D3	43	D29
7	D4	42	D28
8	D5	41	D27
9	$\overline{OEDB}$	40	D26
10	D6	39	D25
11	D7	38	D24
12	GND	37	GND
13	D8	36	D23
14	D9	35	D22
15	D10	34	D21
16	D11	33	D20
17	D12	32	D19
18	D13	31	D18
19	D14	30	D17
20	D15	29	D16
21	CS6	28	CS0
22	CS5	27	CS1
23	CS4	26	CS2
24	$\overline{OECS}$	25	CS3

74634 (68-pin chip carrier)

Pin	Signal	Pin	Signal	Pin	Signal	Pin	Signal
1	VCC	18	GND	35	$\overline{OECB}$	52	GND
2	NC	19	D8	36	CS3	53	D24
3	$\overline{MERR}$	20	D9	37	CS2	54	D25
4	$\overline{ERR}$	21	NC	38	CS1	55	NC
5	D0	22	D10	39	CS0	56	D26
6	D1	23	D11	40	D16	57	D27
7	D2	24	D12	41	D17	58	D28
8	NC	25	D13	42	NC	59	NC
9	NC	26	D14	43	NC	60	NC
10	NC	27	NC	44	D18	61	NC
11	D3	28	NC	45	D19	62	NC
12	D4	29	NC	46	D20	63	D29
13	D5	30	D15	47	D21	64	D30
14	$\overline{OEDB}$	31	NC	48	NC	65	D31
15	D6	32	CS6	49	D22	66	S0
16	D7	33	CS5	50	D23	67	S1
17	GND	34	CS4	51	GND	68	VCC

74635 (DIP-48)

Pin	Signal	Pin	Signal
1	$\overline{MERR}$	48	VCC
2	$\overline{ERR}$	47	S1
3	D0	46	S0
4	D1	45	D31
5	D2	44	D30
6	D3	43	D29
7	D4	42	D28
8	D5	41	D27
9	$\overline{OEDB}$	40	D26
10	D6	39	D25
11	D7	38	D24
12	GND	37	GND
13	D8	36	D23
14	D9	35	D22
15	D10	34	D21
16	D11	33	D20
17	D12	32	D19
18	D13	31	D18
19	D14	30	D17
20	D15	29	D16
21	CS6	28	CS0
22	CS5	27	CS1
23	CS4	26	CS2
24	$\overline{OECS}$	25	CS3

74635 (68-pin chip carrier)

Pin	Signal	Pin	Signal	Pin	Signal	Pin	Signal
1	VCC	18	GND	35	$\overline{OECS}$	52	GND
2	NC	19	D8	36	CS3	53	D24
3	$\overline{MERR}$	20	D9	37	CS2	54	D25
4	$\overline{ERR}$	21	NC	38	CS1	55	NC
5	D0	22	D10	39	CS0	56	D26
6	D1	23	D11	40	D16	57	D27
7	D2	24	D12	41	D17	58	D28
8	NC	25	D13	42	NC	59	NC
9	NC	26	D14	43	NC	60	NC
10	NC	27	NC	44	D18	61	NC
11	D3	28	NC	45	D19	62	NC
12	D4	29	NC	46	D20	63	D29
13	D5	30	D15	47	D21	64	D30
14	$\overline{OEDB}$	31	NC	48	NC	65	D31
15	D6	32	CS6	49	D22	66	S0
16	D7	33	CS5	50	D23	67	S1
17	GND	34	CS4	51	GND	68	VCC

74636 (DIP-20)

Pin	Signal	Pin	Signal
1	DEF	20	VCC
2	D0	19	SEF
3	D1	18	S1
4	D2	17	S0
5	D3	16	CB0
6	D4	15	CB1
7	D5	14	CB2
8	D6	13	CB3
9	D7	12	NC
10	GND	11	CB4

74636 (20-pin chip carrier)

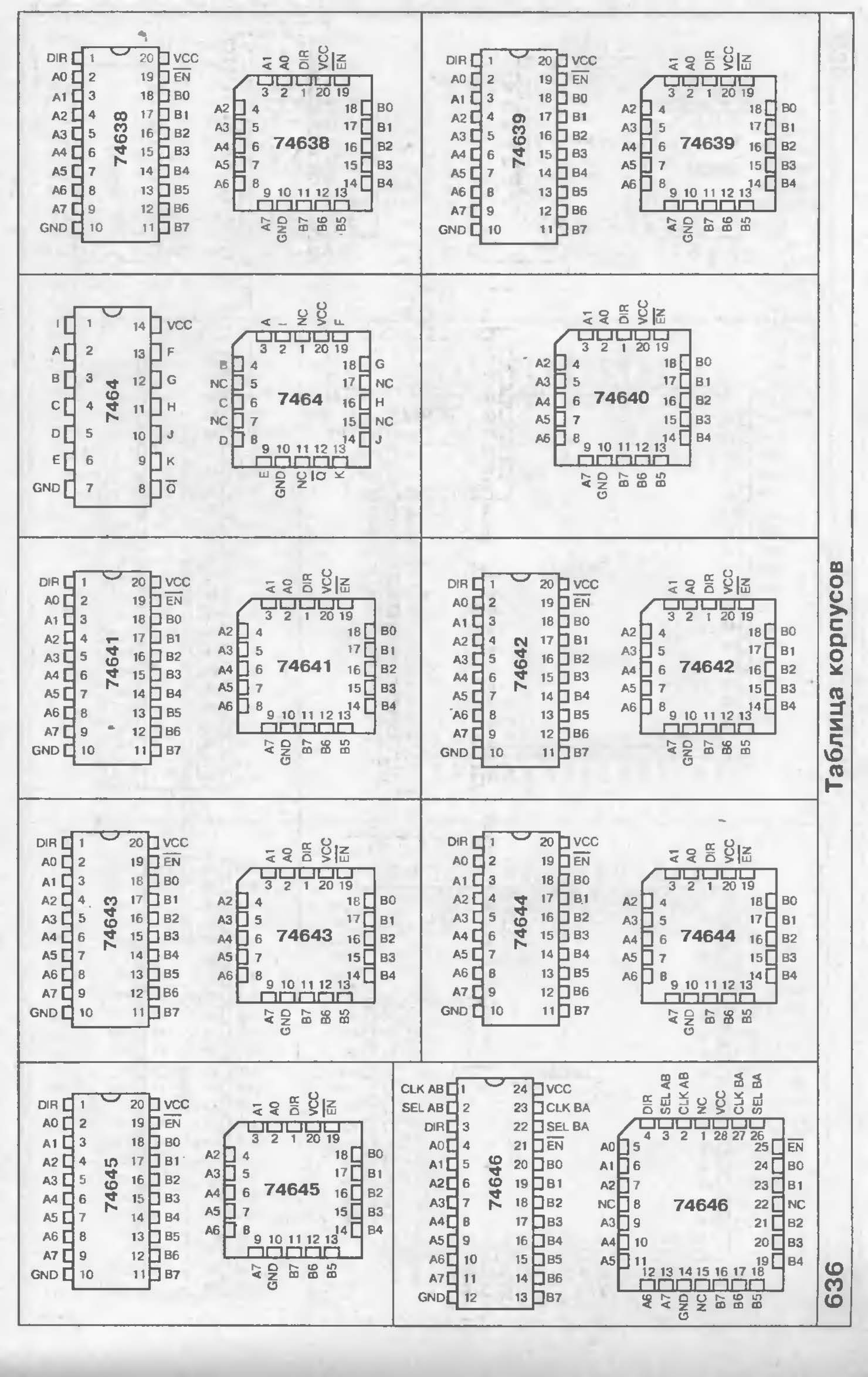
Pin	Signal	Pin	Signal
1	DEF	11	CB4
2	D0	12	NC
3	D1	13	CB3
4	D2	14	CB2
5	D3	15	CB1
6	D4	16	CB0
7	D5	17	S0
8	D6	18	S1
9	D7	19	SEF
10	GND	20	VCC

74637 (DIP-20)

Pin	Signal	Pin	Signal
1	DEF	20	VCC
2	D0	19	SEF
3	D1	18	S1
4	D2	17	S0
5	D3	16	CB0
6	D4	15	CB1
7	D5	14	CB2
8	D6	13	CB3
9	D7	12	NC
10	GND	11	CB4

74637 (20-pin chip carrier)

Pin	Signal	Pin	Signal
1	DEF	11	CB4
2	D0	12	NC
3	D1	13	CB3
4	D2	14	CB2
5	D3	15	CB1
6	D4	16	CB0
7	D5	17	S0
8	D6	18	S1
9	D7	19	SEF
10	GND	20	VCC


74638
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74646

74647

Signal	Pin	Pin	Signal
CLK AB	1	24	VCC
SEL AB	2	23	CLK BA
DIR	3	22	SEL BA
A0	4	21	$\overline{EN}$
A1	5	20	B0
A2	6	19	B1
A3	7	18	B2
A4	8	17	B3
A5	9	16	B4
A6	10	15	B5
A7	11	14	B6
GND	12	13	B7

74648

Signal	Pin	Pin	Signal
CLK AB	1	24	VCC
SEL AB	2	23	CLK BA
DIR	3	22	SEL BA
A0	4	21	$\overline{EN}$
A1	5	20	B0
A2	6	19	B1
A3	7	18	B2
A4	8	17	B3
A5	9	16	B4
A6	10	15	B5
A7	11	14	B6
GND	12	13	B7

74649

Signal	Pin	Pin	Signal
CLK AB	1	24	VCC
SEL AB	2	23	CLK BA
DIR	3	22	SEL BA
A0	4	21	$\overline{EN}$
A1	5	20	B0
A2	6	19	B1
A3	7	18	B2
A4	8	17	B3
A5	9	16	B4
A6	10	15	B5
A7	11	14	B6
GND	12	13	B7

7465

Signal	Pin	Pin	Signal
I	1	14	VCC
A	2	13	F
B	3	12	G
C	4	11	H
D	5	10	J
E	6	9	K
GND	7	6	Q

74647 (PLCC)

Top	Left	Right	Bottom
DIR 4	A0 5	25 $\overline{EN}$	12 A6
SEL AB 3	A1 6	24 B0	13 A7
CLK AB 2	A2 7	23 B1	14 GND
NC 1	NC 8	22 NC	15 NC
VCC 28	A3 9	21 B2	16 B7
CLK BA 27	A4 10	20 B3	17 B6
SEL BA 26	A5 11	19 B4	16 B5

74648 (PLCC)

Top	Left	Right	Bottom
DIR 4	A0 5	25 $\overline{EN}$	12 A6
SEL AB 3	A1 6	24 B0	13 A7
CLK AB 2	A2 7	23 B1	14 GND
NC 1	NC 8	22 NC	15 NC
VCC 28	A3 9	21 B2	16 B7
CLK BA 27	A4 10	20 B3	17 B6
SEL BA 26	A5 11	19 B4	18 B5

74649 (PLCC)

Top	Left	Right	Bottom
DIR 4	A0 5	25 $\overline{EN}$	12 A6
SEL AB 3	A1 6	24 B0	13 A7
CLK AB 2	A2 7	23 B1	14 GND
NC 1	NC 8	22 NC	15 NC
VCC 28	A3 9	21 B2	16 B7
CLK BA 27	A4 10	20 B3	17 B6
SEL BA 26	A5 11	19 B4	18 B5

74651

Signal	Pin	Pin	Signal
CLK AB	1	24	VCC
SEL AB	2	23	CLK BA
ENAB	3	22	SEL BA
A0	4	21	$\overline{ENBA}$
A1	5	20	B0
A2	6	19	B1
A3	7	18	B2
A4	8	17	B3
A5	9	16	B4
A6	10	15	B5
A7	11	14	B6
GND	12	13	B7

74652

Signal	Pin	Pin	Signal
CLK AB	1	24	VCC
SEL AB	2	23	CLK BA
ENA8	3	22	SEL BA
A0	4	21	$\overline{ENBA}$
A1	5	20	B0
A2	6	19	B1
A3	7	16	B2
A4	6	17	B3
A5	9	16	B4
A6	10	15	B5
A7	11	14	B6
GND	12	13	B7

74653

Signal	Pin	Pin	Signal
CLK AB	1	24	VCC
SEL AB	2	23	CLK BA
ENAB	3	22	SEL BA
A0	4	21	$\overline{ENBA}$
A1	5	20	B0
A2	6	19	B1
A3	7	18	B2
A4	8	17	B3
A5	9	16	B4
A6	10	15	B5
A7	11	14	B6
GND	12	13	B7

74651 (PLCC)

Top	Left	Right	Bottom
ENAB 4	A0 5	25 $\overline{ENBA}$	12 A6
SEL AB 3	A1 6	24 B0	13 A7
CLK AB 2	A2 7	23 B1	14 GND
NC 1	NC 8	22 NC	15 NC
VCC 26	A3 9	21 B2	16 B7
CLK BA 27	A4 10	20 B3	17 B6
SEL BA 26	A5 11	19 B4	16 B5

74652 (PLCC)

Top	Left	Right	Bottom
ENAB 4	A0 5	25 $\overline{ENBA}$	12 A6
SEL AB 3	A1 6	24 B0	13 A7
CLK AB 2	A2 7	23 B1	14 GND
NC 1	NC 8	22 NC	15 NC
VCC 28	A3 9	21 B2	16 B7
CLK BA 27	A4 10	20 B3	17 B6
SEL BA 26	A5 11	19 B4	18 B5

74653 (PLCC)

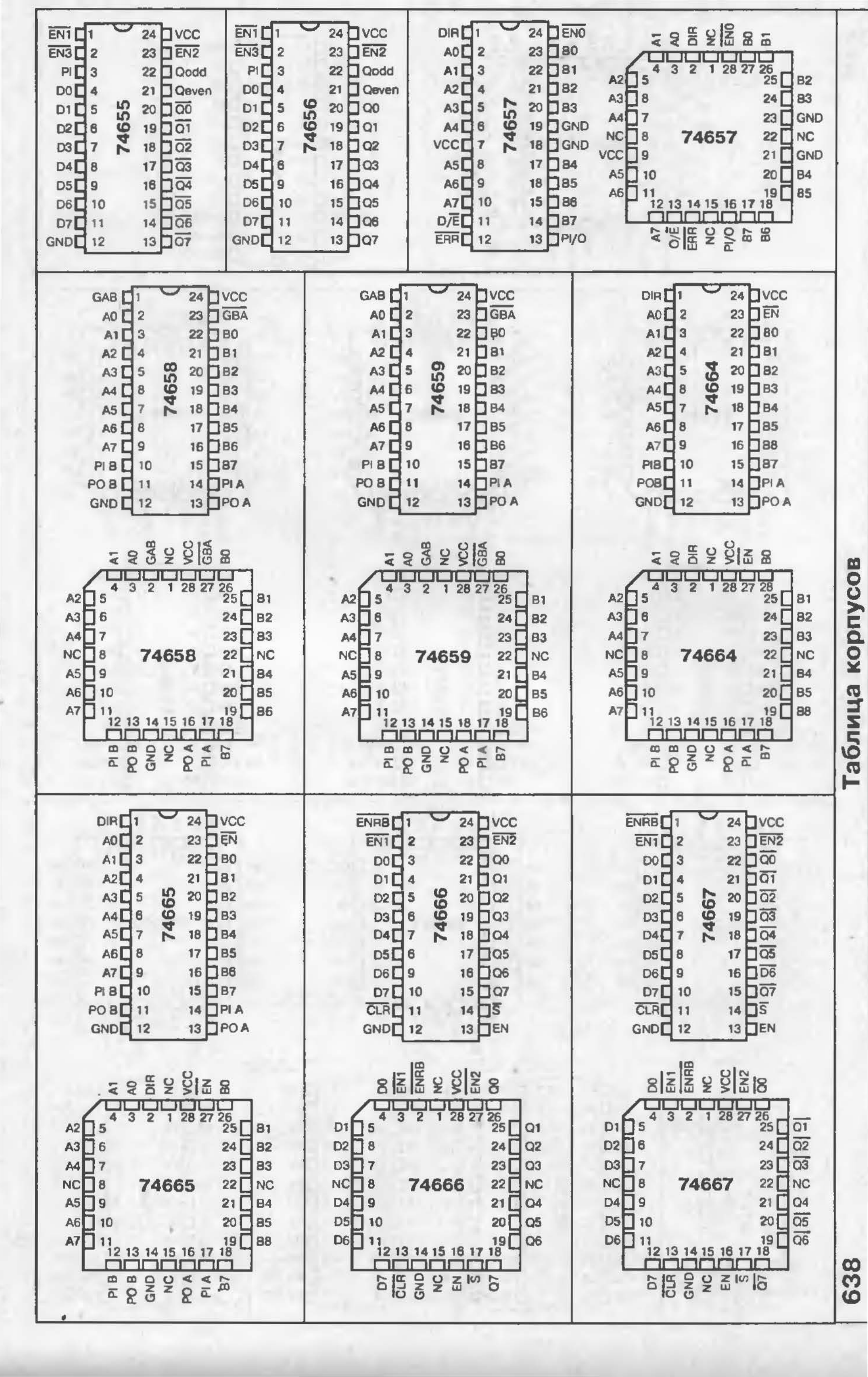
Top	Left	Right	Bottom
ENAB 4	A0 5	25 $\overline{ENBA}$	12 A6
SEL AB 3	A1 6	24 B0	13 A7
CLK AB 2	A2 7	23 B1	14 GND
NC 1	NC 8	22 NC	15 NC
VCC 28	A3 9	21 B2	16 B7
CLK BA 27	A4 10	20 B3	17 B6
SEL BA 26	A5 11	19 B4	18 B5

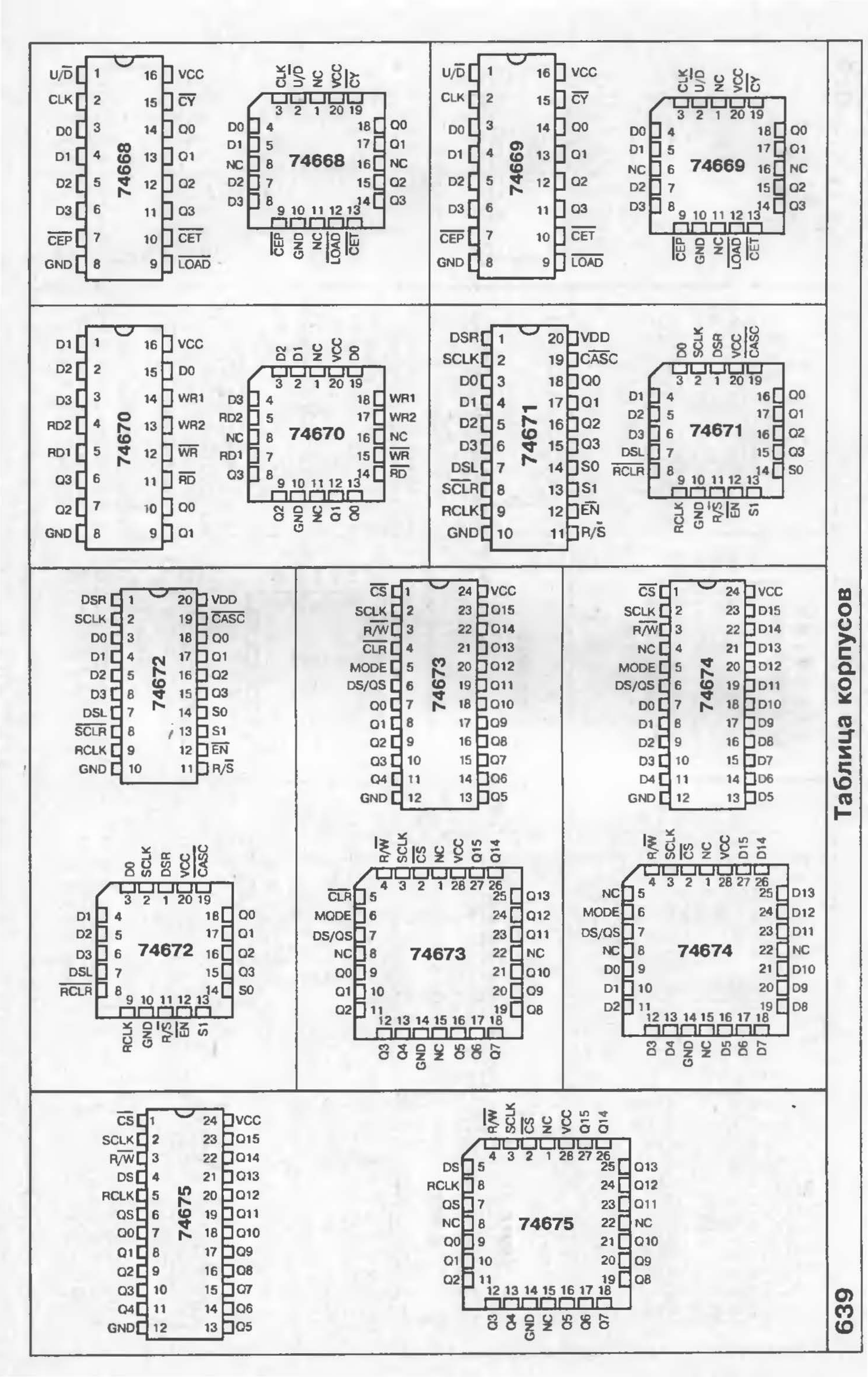
74654

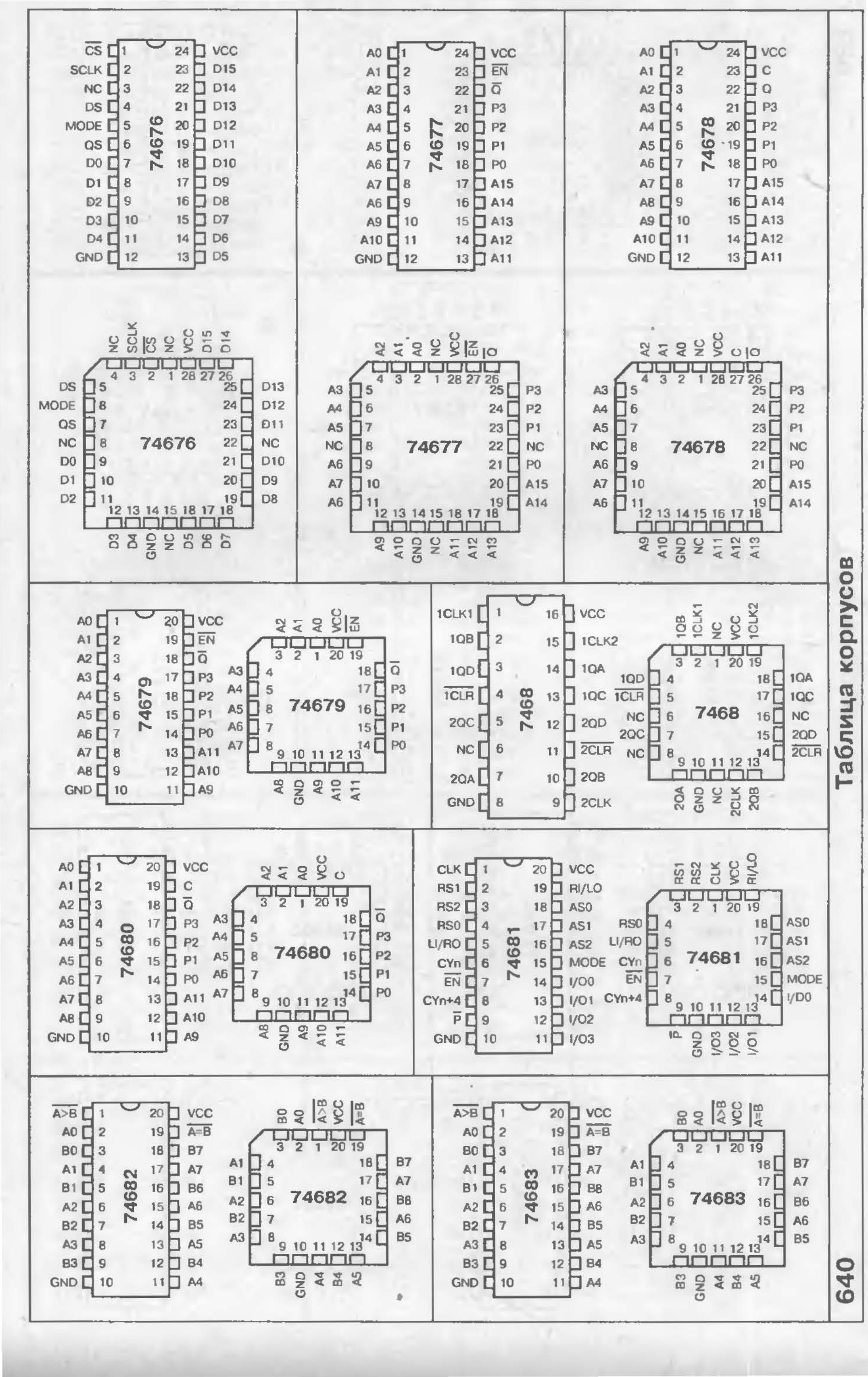
Signal	Pin	Pin	Signal
CLK AB	1	24	VCC
SEL AB	2	23	CLK BA
ENAB	3	22	SEL BA
A0	4	21	$\overline{ENBA}$
A1	5	20	B0
A2	6	19	B1
A3	7	18	B2
A4	8	17	B3
A5	9	16	B4
A6	10	15	B5
A7	11	14	B6
GND	12	13	B7

74654 (PLCC)

Top	Left	Right	Bottom
ENAB 4	A0 5	25 $\overline{ENBA}$	12 A6
SEL AB 3	A1 6	24 B0	13 A7
CLK AB 2	A2 7	23 B1	14 GND
NC 1	NC 8	22 NC	15 NC
VCC 28	A3 9	21 B2	16 B7
CLK BA 27	A4 10	20 B3	17 B6
SEL BA 26	A5 11	19 B4	18 B5


74655
EN1 1 24 VCC
EN3 2 23 EN2
PI 3 22 Qodd
D0 4 21 Qeven
D1 5 20 Q0
D2 6 19 Q1
D3 7 18 Q2
D4 8 17 Q3
D5 9 16 Q4
D6 10 15 Q5
D7 11 14 Q6
GND 12 13 Q7
74656
EN1 1 24 VCC
EN3 2 23 EN2
PI 3 22 Qodd
D0 4 21 Qeven
D1 5 20 Q0
D2 6 19 Q1
D3 7 18 Q2
D4 8 17 Q3
D5 9 16 Q4
D6 10 15 Q5
D7 11 14 Q6
GND 12 13 Q7
74657
DIR 1 24 EN0
A0 2 23 B0
A1 3 22 B1
A2 4 21 B2
A3 5 20 B3
A4 6 19 GND
VCC 7 18 GND
A5 8 17 B4
A6 9 16 B5
A7 10 15 B6
D/E 11 14 B7
ERR 12 13 PI/O
74657
A1 A0 DIR NC EN0 B0 B1
4 3 2 1 28 27 26
A2 5 25 B2
A3 6 24 B3
A4 7 23 GND
NC 8 22 NC
VCC 9 21 GND
A5 10 20 B4
A6 11 19 B5
12 13 14 15 16 17 18
A7 O/E ERR NC PI/O B7 B6
74658
GAB 1 24 VCC
A0 2 23 GBA
A1 3 22 B0
A2 4 21 B1
A3 5 20 B2
A4 6 19 B3
A5 7 18 B4
A6 8 17 B5
A7 9 16 B6
PI B 10 15 B7
PO B 11 14 PI A
GND 12 13 PO A
74659
GAB 1 24 VCC
A0 2 23 GBA
A1 3 22 B0
A2 4 21 B1
A3 5 20 B2
A4 6 19 B3
A5 7 18 B4
A6 8 17 B5
A7 9 16 B6
PI B 10 15 B7
PO B 11 14 PI A
GND 12 13 PO A
74664
DIR 1 24 VCC
A0 2 23 EN
A1 3 22 B0
A2 4 21 B1
A3 5 20 B2
A4 6 19 B3
A5 7 18 B4
A6 8 17 B5
A7 9 16 B6
PIB 10 15 B7
POB 11 14 PI A
GND 12 13 PO A
74658
A1 A0 GAB NC VCC GBA B0
4 3 2 1 28 27 26
A2 5 25 B1
A3 6 24 B2
A4 7 23 B3
NC 8 22 NC
A5 9 21 B4
A6 10 20 B5
A7 11 19 B6
12 13 14 15 16 17 18
PI B PO B GND NC PO A PI A B7
74659
A1 A0 GAB NC VCC GBA B0
4 3 2 1 28 27 26
A2 5 25 B1
A3 6 24 B2
A4 7 23 B3
NC 8 22 NC
A5 9 21 B4
A6 10 20 B5
A7 11 19 B6
12 13 14 15 16 17 18
PI B PO B GND NC PO A PI A B7
74664
A1 A0 DIR NC VCC EN B0
4 3 2 1 28 27 26
A2 5 25 B1
A3 6 24 B2
A4 7 23 B3
NC 8 22 NC
A5 9 21 B4
A6 10 20 B5
A7 11 19 B6
12 13 14 15 16 17 18
PI B PO B GND NC PO A PI A B7
74665
DIR 1 24 VCC
A0 2 23 EN
A1 3 22 B0
A2 4 21 B1
A3 5 20 B2
A4 6 19 B3
A5 7 18 B4
A6 8 17 B5
A7 9 16 B6
PI B 10 15 B7
PO B 11 14 PI A
GND 12 13 PO A
74666
ENRB 1 24 VCC
EN1 2 23 EN2
D0 3 22 Q0
D1 4 21 Q1
D2 5 20 Q2
D3 6 19 Q3
D4 7 18 Q4
D5 8 17 Q5
D6 9 16 Q6
D7 10 15 Q7
CLR 11 14 S
GND 12 13 EN
74667
ENRB 1 24 VCC
EN1 2 23 EN2
D0 3 22 Q0
D1 4 21 Q1
D2 5 20 Q2
D3 6 19 Q3
D4 7 18 Q4
D5 8 17 Q5
D6 9 16 Q6
D7 10 15 Q7
CLR 11 14 S
GND 12 13 EN
74665
A1 A0 DIR NC VCC EN B0
4 3 2 1 28 27 26
A2 5 25 B1
A3 6 24 B2
A4 7 23 B3
NC 8 22 NC
A5 9 21 B4
A6 10 20 B5
A7 11 19 B6
12 13 14 15 16 17 18
PI B PO B GND NC PO A PI A B7
74666
D0 EN1 ENRB NC VCC EN2 Q0
4 3 2 1 28 27 26
D1 5 25 Q1
D2 6 24 Q2
D3 7 23 Q3
NC 8 22 NC
D4 9 21 Q4
D5 10 20 Q5
D6 11 19 Q6
12 13 14 15 16 17 18
D7 CLR GND NC EN S Q7
74667
D0 EN1 ENRB NC VCC EN2 Q0
4 3 2 1 28 27 26
D1 5 25 Q1
D2 6 24 Q2
D3 7 23 Q3
NC 8 22 NC
D4 9 21 Q4
D5 10 20 Q5
D6 11 19 Q6
12 13 14 15 16 17 18
D7 CLR GND NC EN S Q7


74668
U/D 1, CLK 2, D0 3, D1 4, D2 5, D3 6, CEP 7, GND 8
16 VCC, 15 CY, 14 Q0, 13 Q1, 12 Q2, 11 Q3, 10 CET, 9 LOAD
74668
CLK 3, U/D 2, NC 1, VCC 20, CY 19
D0 4, D1 5, NC 6, D2 7, D3 8
18 Q0, 17 Q1, 16 NC, 15 Q2, 14 Q3
CEP 9, GND 10, NC 11, LOAD 12, CET 13
74669
U/D 1, CLK 2, D0 3, D1 4, D2 5, D3 6, CEP 7, GND 8
16 VCC, 15 CY, 14 Q0, 13 Q1, 12 Q2, 11 Q3, 10 CET, 9 LOAD
74669
CLK 3, U/D 2, NC 1, VCC 20, CY 19
D0 4, D1 5, NC 6, D2 7, D3 8
18 Q0, 17 Q1, 16 NC, 15 Q2, 14 Q3
CEP 9, GND 10, NC 11, LOAD 12, CET 13
74670
D1 1, D2 2, D3 3, RD2 4, RD1 5, Q3 6, Q2 7, GND 8
16 VCC, 15 D0, 14 WR1, 13 WR2, 12 WR, 11 RD, 10 Q0, 9 Q1
74670
D2 3, D1 2, NC 1, VCC 20, D0 19
D3 4, RD2 5, NC 6, RD1 7, Q3 8
18 WR1, 17 WR2, 16 NC, 15 WR, 14 RD
Q2 9, GND 10, NC 11, Q1 12, Q0 13
74671
DSR 1, SCLK 2, D0 3, D1 4, D2 5, D3 6, DSL 7, SCLR 8, RCLK 9, GND 10
20 VDD, 19 CASC, 18 Q0, 17 Q1, 16 Q2, 15 Q3, 14 S0, 13 S1, 12 EN, 11 R/S
74671
D0 3, SCLK 2, DSR 1, VCC 20, CASC 19
D1 4, D2 5, D3 6, DSL 7, RCLR 8
16 Q0, 17 Q1, 16 Q2, 15 Q3, 14 S0
RCLK 9, GND 10, R/S 11, EN 12, S1 13
74672
DSR 1, SCLK 2, D0 3, D1 4, D2 5, D3 8, DSL 7, SCLR 8, RCLK 9, GND 10
20 VDD, 19 CASC, 18 Q0, 17 Q1, 16 Q2, 15 Q3, 14 S0, 13 S1, 12 EN, 11 R/S
74672
D0 3, SCLK 2, DSR 1, VCC 20, CASC 19
D1 4, D2 5, D3 6, DSL 7, RCLR 8
18 Q0, 17 Q1, 16 Q2, 15 Q3, 14 S0
RCLK 9, GND 10, R/S 11, EN 12, S1 13
74673
CS 1, SCLK 2, R/W 3, CLR 4, MODE 5, DS/QS 6, Q0 7, Q1 8, Q2 9, Q3 10, Q4 11, GND 12
24 VCC, 23 Q15, 22 Q14, 21 Q13, 20 Q12, 19 Q11, 18 Q10, 17 Q9, 16 Q8, 15 Q7, 14 Q6, 13 Q5
74673
R/W 4, SCLK 3, CS 2, NC 1, VCC 28, Q15 27, Q14 26
CLR 5, MODE 6, DS/QS 7, NC 8, Q0 9, Q1 10, Q2 11
25 Q13, 24 Q12, 23 Q11, 22 NC, 21 Q10, 20 Q9, 19 Q8
Q3 12, Q4 13, GND 14, NC 15, Q5 16, Q6 17, Q7 18
74674
CS 1, SCLK 2, R/W 3, NC 4, MODE 5, DS/QS 6, D0 7, D1 8, D2 9, D3 10, D4 11, GND 12
24 VCC, 23 D15, 22 D14, 21 D13, 20 D12, 19 D11, 18 D10, 17 D9, 16 D8, 15 D7, 14 D6, 13 D5
74674
R/W 4, SCLK 3, CS 2, NC 1, VCC 28, D15 27, D14 26
NC 5, MODE 6, DS/QS 7, NC 8, D0 9, D1 10, D2 11
25 D13, 24 D12, 23 D11, 22 NC, 21 D10, 20 D9, 19 D8
D3 12, D4 13, GND 14, NC 15, D5 16, D6 17, D7 18
74675
CS 1, SCLK 2, R/W 3, DS 4, RCLK 5, QS 6, Q0 7, Q1 8, Q2 9, Q3 10, Q4 11, GND 12
24 VCC, 23 Q15, 22 Q14, 21 Q13, 20 Q12, 19 Q11, 18 Q10, 17 Q9, 16 Q8, 15 Q7, 14 Q6, 13 Q5
74675
R/W 4, SCLK 3, CS 2, NC 1, VCC 28, Q15 27, Q14 26
DS 5, RCLK 8, QS 7, NC 8, Q0 9, Q1 10, Q2 11
25 Q13, 24 Q12, 23 Q11, 22 NC, 21 Q10, 20 Q9, 19 Q8
Q3 12, Q4 13, GND 14, NC 15, Q5 16, Q6 17, Q7 18


74676
CS SCLK NC DS MODE QS D0 D1 D2 D3 D4 GND
1 2 3 4 5 6 7 8 9 10 11 12
24 23 22 21 20 19 18 17 16 15 14 13
VCC D15 D14 D13 D12 D11 D10 D9 D8 D7 D6 D5
74677
A0 A1 A2 A3 A4 A5 A6 A7 A6 A9 A10 GND
VCC EN Q P3 P2 P1 P0 A15 A14 A13 A12 A11
74678
A0 A1 A2 A3 A4 A5 A6 A7 A8 A9 A10 GND
VCC C Q P3 P2 P1 P0 A15 A14 A13 A12 A11
74676
NC SCLK CS NC VCC D15 D14
DS MODE QS NC D0 D1 D2
D13 D12 D11 NC D10 D9 D8
D3 D4 GND NC D5 D6 D7
74677
A2 A1 A0 NC VCC EN Q
A3 A4 A5 NC A6 A7 A6
P3 P2 P1 NC P0 A15 A14
A9 A10 GND NC A11 A12 A13
74678
A2 A1 A0 NC VCC C Q
A3 A4 A5 NC A6 A7 A6
P3 P2 P1 NC P0 A15 A14
A9 A10 GND NC A11 A12 A13
74679
A0 A1 A2 A3 A4 A5 A6 A7 A8 GND
VCC EN Q P3 P2 P1 P0 A11 A10 A9
74679
A2 A1 A0 VCC EN
A3 A4 A5 A6 A7
Q P3 P2 P1 P0
A8 GND A9 A10 A11
7468
1CLK1 1QB 1QD 1CLR 2QC NC 2QA GND
VCC 1CLK2 1QA 1QC 2QD 2CLR 2QB 2CLK
7468
1QB 1CLK1 NC VCC 1CLK2
1QD 1CLR NC 2QC NC
1QA 1QC NC 2QD 2CLR
2QA GND NC 2CLK 2QB
74680
A0 A1 A2 A3 A4 A5 A6 A7 A8 GND
VCC C Q P3 P2 P1 P0 A11 A10 A9
74680
A2 A1 A0 VCC C
A3 A4 A5 A6 A7
Q P3 P2 P1 P0
A8 GND A9 A10 A11
74681
CLK RS1 RS2 RS0 LI/RO CYn EN CYn+4 P GND
VCC RI/LO AS0 AS1 AS2 MODE I/O0 I/O1 I/O2 I/O3
74681
RS1 RS2 CLK VCC RI/LO
RS0 LI/RO CYn EN CYn+4
AS0 AS1 AS2 MODE I/D0
P GND I/O3 I/O2 I/O1
74682
A>B A0 B0 A1 B1 A2 B2 A3 B3 GND
VCC A=B B7 A7 B6 A6 B5 A5 B4 A4
74682
B0 A0 A>B VCC A=B
A1 B1 A2 B2 A3
B7 A7 B8 A6 B5
B3 GND A4 B4 A5
74683
A>B A0 B0 A1 B1 A2 B2 A3 B3 GND
VCC A=B B7 A7 B8 A6 B5 A5 B4 A4
74683
B0 A0 A>B VCC A=B
A1 B1 A2 B2 A3
B7 A7 B6 A6 B5
B3 GND A4 B4 A5

74684 (DIP)

Pin	Signal	Pin	Signal
1	$\overline{A>B}$	20	VCC
2	A0	19	$\overline{A=B}$
3	B0	18	B7
4	A1	17	A7
5	B1	16	B6
6	A2	15	A6
7	B2	14	B5
8	A3	13	A5
9	B3	12	B4
10	GND	11	A4

74684 (PLCC)

Pin	Signal	Pin	Signal	Pin	Signal	Pin	Signal
3	B0	4	A1	9	B3	18	B7
2	A0	5	B1	10	GND	17	A7
1	$\overline{A>B}$	6	A2	11	A4	16	B6
20	VCC	7	B2	12	B4	15	A6
19	$\overline{A=B}$	8	A3	13	A5	14	B5

74685 (DIP)

Pin	Signal	Pin	Signal
1	$\overline{A>B}$	20	VCC
2	A0	19	$\overline{A=B}$
3	B0	18	B7
4	A1	17	A7
5	B1	16	B6
6	A2	15	A6
7	B2	14	B5
8	A3	13	A5
9	B3	12	B4
10	GND	11	A4

74685 (PLCC)

Pin	Signal	Pin	Signal	Pin	Signal	Pin	Signal
3	B0	4	A1	9	B3	18	B7
2	A0	5	B1	10	GND	17	A7
1	$\overline{A>B}$	6	A2	11	A4	16	B6
20	VCC	7	B2	12	B4	15	A8
19	$\overline{A=B}$	8	A3	13	A5	14	B5

74686 (DIP)

Pin	Signal	Pin	Signal
1	$\overline{A>B}$	24	VCC
2	$\overline{EN1}$	23	$\overline{EN2}$
3	A0	22	$\overline{A=B}$
4	B0	21	B7
5	A1	20	A7
6	B1	19	NC
7	NC	18	B6
8	A2	17	A6
9	B2	16	B5
10	A3	15	A5
11	B3	14	B4
12	GND	13	A4

74687 (DIP)

Pin	Signal	Pin	Signal
1	$\overline{A>B}$	24	VCC
2	$\overline{EN1}$	23	$\overline{EN2}$
3	A0	22	$\overline{A=B}$
4	B0	21	B7
5	A1	20	A7
6	B1	19	NC
7	NC	18	B6
8	A2	17	A6
9	B2	16	B5
10	A3	15	A5
11	B3	14	B4
12	GND	13	A4

74688 (DIP)

Pin	Signal	Pin	Signal
1	$\overline{EN}$	20	VCC
2	A0	19	$\overline{A=B}$
3	B0	18	B7
4	A1	17	A7
5	B1	16	B6
6	A2	15	A6
7	B2	14	B5
8	A3	13	A5
9	B3	12	B4
10	GND	11	A4

74686 (PLCC)

Pin	Signal	Pin	Signal	Pin	Signal	Pin	Signal
4	A0	5	B0	12	A3	25	B7
3	$\overline{ENT}$	6	A1	13	B3	24	A7
2	$\overline{A>B}$	7	B1	14	GND	23	NC
1	NC	8	NC	15	NC	22	NC
28	VCC	9	NC	16	A4	21	B6
27	$\overline{EN2}$	10	A2	17	B4	20	A6
26	$\overline{A=B}$	11	B2	18	A5	19	B5

74687 (PLCC)

Pin	Signal	Pin	Signal	Pin	Signal	Pin	Signal
4	A0	5	B0	12	A3	25	B7
3	$\overline{ENT}$	6	A1	13	B3	24	A7
2	$\overline{A>B}$	7	B1	14	GND	23	NC
1	NC	6	NC	15	NC	22	NC
28	VCC	9	NC	16	A4	21	B6
27	$\overline{EN2}$	10	A2	17	B4	20	A6
26	$\overline{A=B}$	11	B2	18	A5	19	B5

74688 (PLCC)

Pin	Signal	Pin	Signal	Pin	Signal	Pin	Signal
3	B0	4	A1	9	B3	18	B7
2	A0	5	B1	10	GND	17	A7
1	$\overline{EN}$	6	A2	11	A4	16	B6
20	VCC	7	B2	12	B4	15	A6
19	$\overline{A=B}$	8	A3	13	A5	14	B5

74689 (DIP)

Pin	Signal	Pin	Signal
1	$\overline{EN}$	20	VCC
2	A0	19	$\overline{A=B}$
3	B0	18	B7
4	A1	17	A7
5	B1	16	B6
8	A2	15	A6
7	B2	14	B5
8	A3	13	A6
9	B3	12	B4
10	GND	11	A4

74689 (PLCC)

Pin	Signal	Pin	Signal	Pin	Signal	Pin	Signal
3	B0	4	A1	9	B3	18	B7
2	A0	5	B1	10	GND	17	A7
1	$\overline{EN}$	6	A2	11	A4	16	B6
20	VCC	7	B2	12	B4	15	A6
19	$\overline{A=B}$	6	A3	13	A5	14	B5

7469 (DIP)

Pin	Signal	Pin	Signal
1	1CLK1	16	VCC
2	1QB	15	1CLK2
3	1QD	14	1QA
4	$\overline{1CLR}$	13	1QC
5	2QC	12	2QD
8	NC	11	$\overline{2CLR}$
7	2QA	10	2QB
8	GND	9	2CLK

7469 (PLCC)

Pin	Signal	Pin	Signal	Pin	Signal	Pin	Signal
3	1QB	4	1QD	9	2QA	18	1QA
2	1CLK1	5	$\overline{1CLR}$	10	GND	17	1QC
1	NC	8	NC	11	NC	16	NC
20	VCC	7	2QC	12	2CLK	15	2QD
19	1CLK2	8	NC	13	2QB	14	$\overline{2CLR}$

74690 (DIP)

Pin	Signal	Pin	Signal
1	$\overline{CCLR}$	20	VCC
2	CCLK	19	RCYQ
3	D0	18	Q0
4	D1	17	Q1
5	D2	16	Q2
6	D3	15	Q3
7	CEN	14	CET
8	$\overline{RCLR}$	13	$\overline{LOAD}$
9	RCLK	12	$\overline{EN}$
10	GND	11	$R/\overline{C}$

74690 (PLCC)

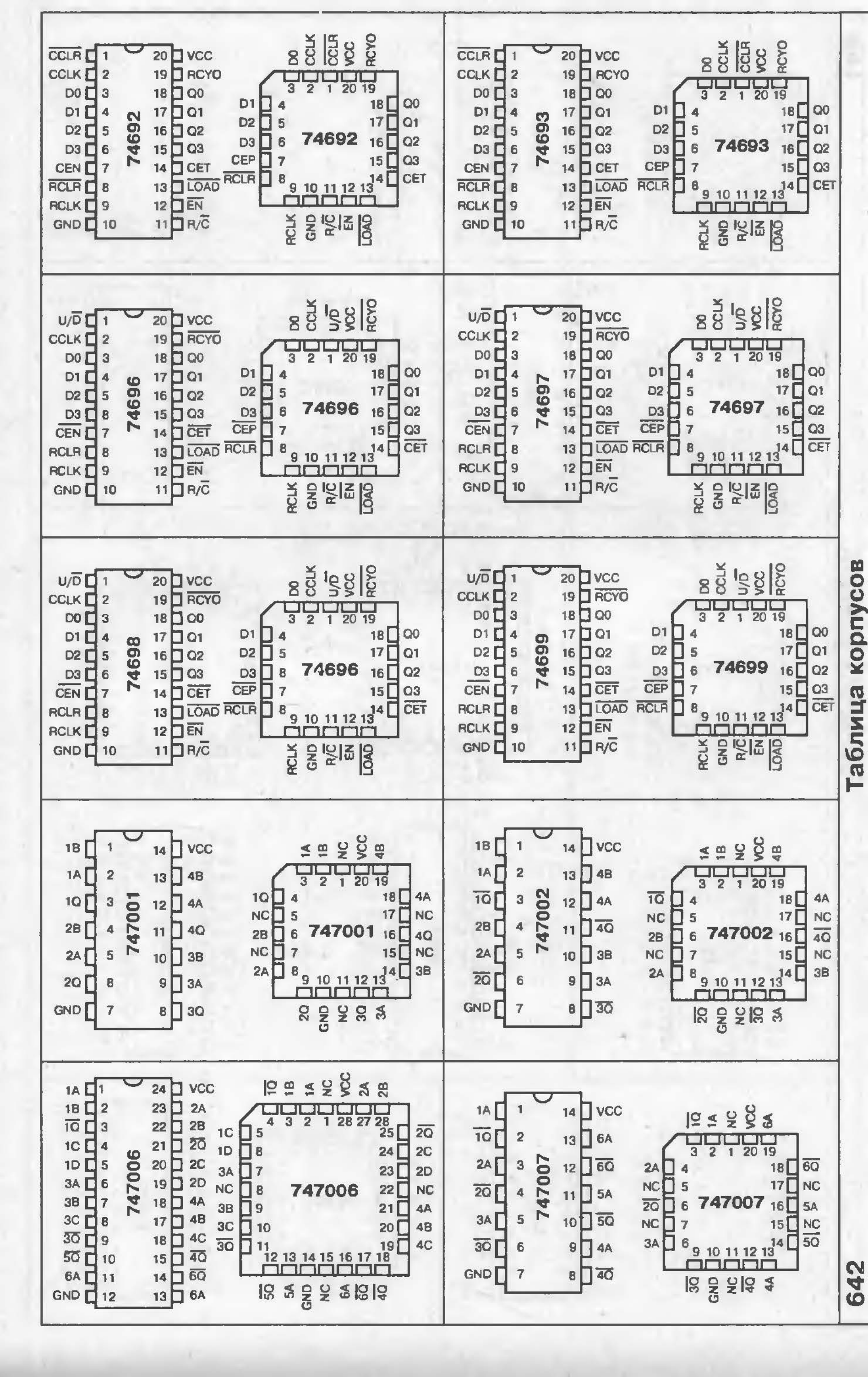
Pin	Signal	Pin	Signal	Pin	Signal	Pin	Signal
3	D0	4	D1	9	RCLK	18	Q0
2	CCLK	5	D2	10	GND	17	Q1
1	$\overline{CCLR}$	6	D3	11	$R/\overline{C}$	16	Q2
20	VCC	7	CEP	12	$\overline{EN}$	15	Q3
19	RCYO	8	$\overline{RCLR}$	13	$\overline{LOAD}$	14	CET

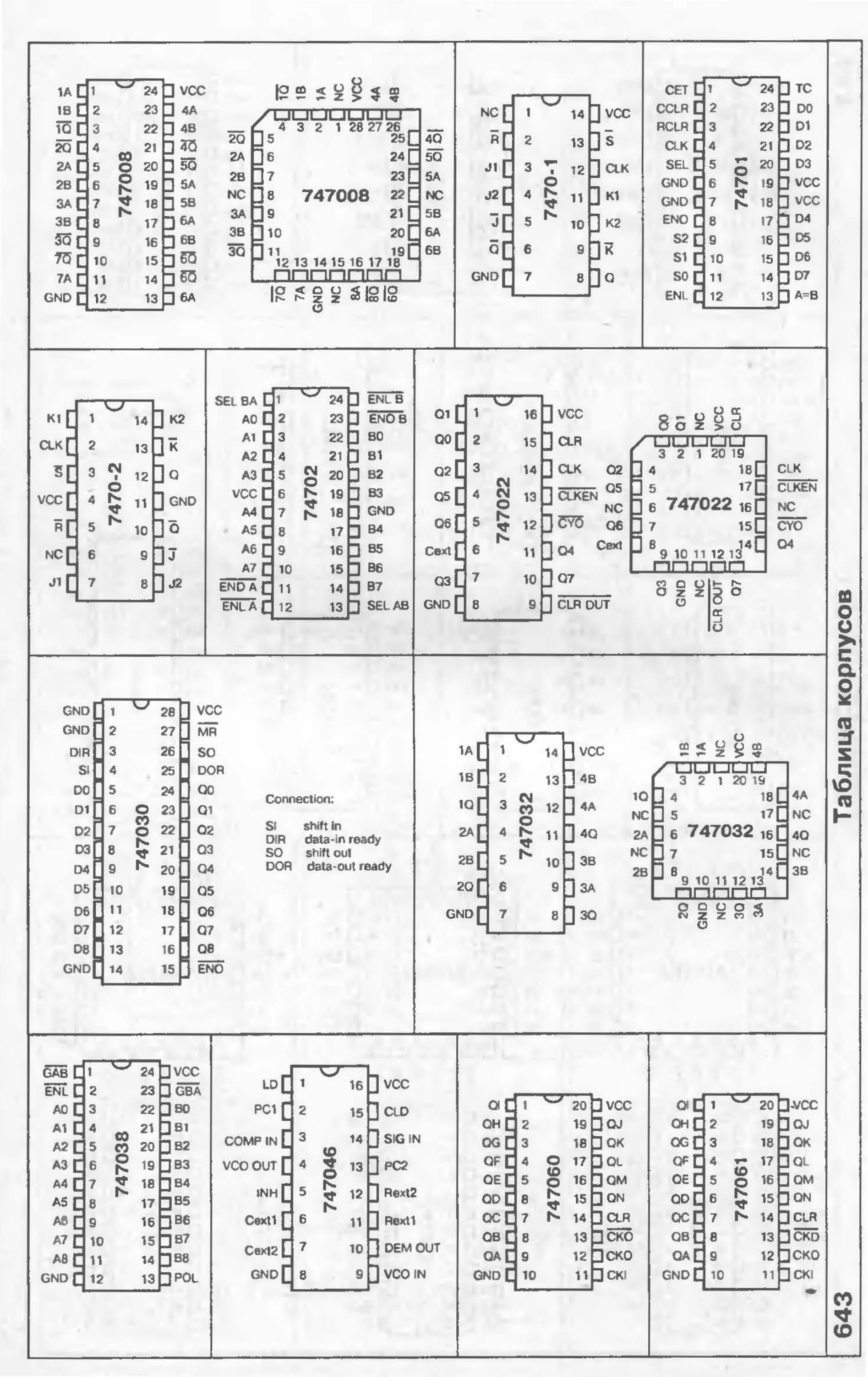
74691 (DIP)

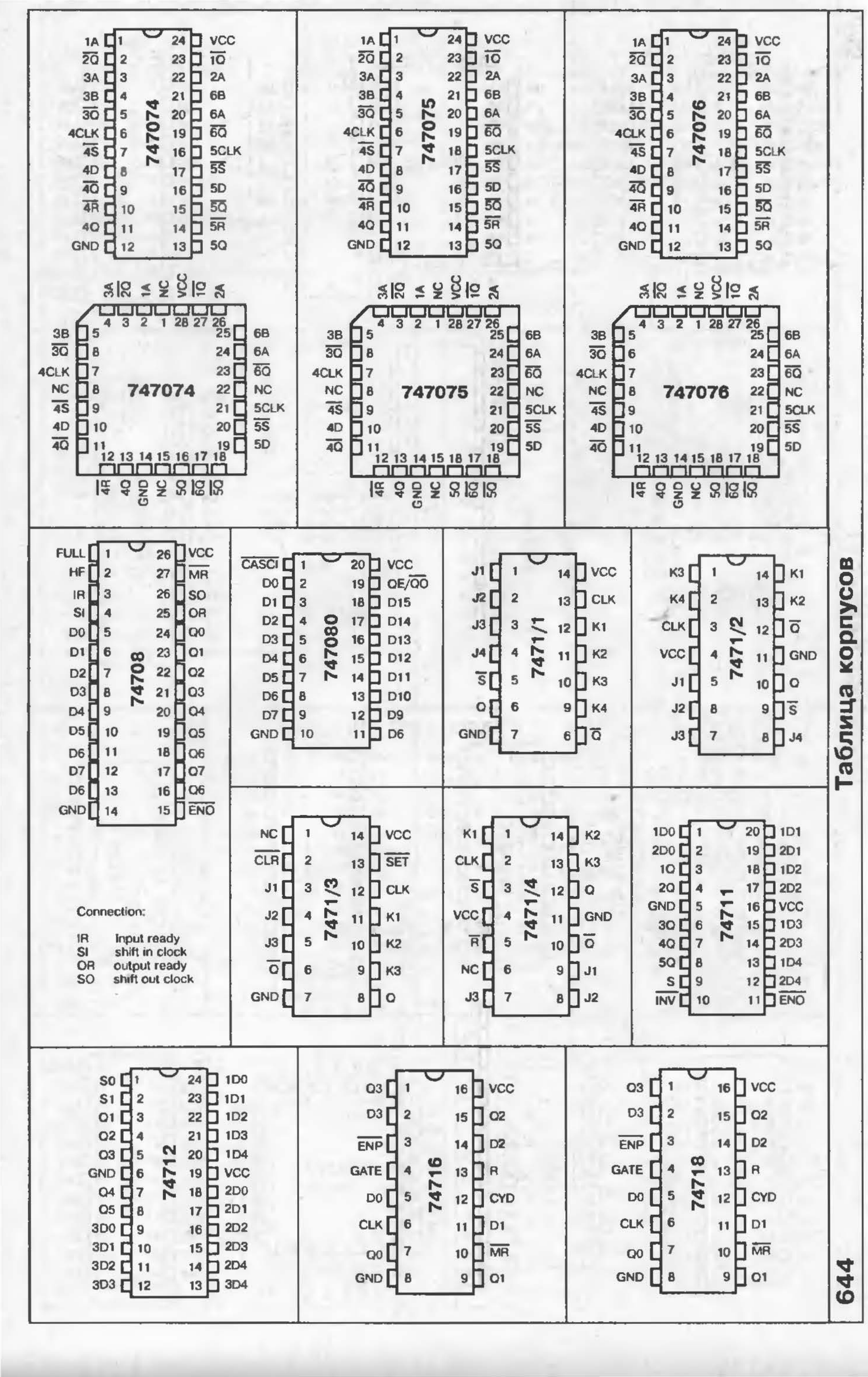
Pin	Signal	Pin	Signal
1	$\overline{CCLR}$	20	VCC
2	CCLK	19	RCYO
3	D0	18	Q0
4	D1	17	Q1
5	D2	16	Q2
6	D3	15	Q3
7	CEN	14	CET
8	$\overline{RCLR}$	13	$\overline{LOAD}$
9	RCLK	12	$\overline{EN}$
10	GND	11	$R/\overline{C}$

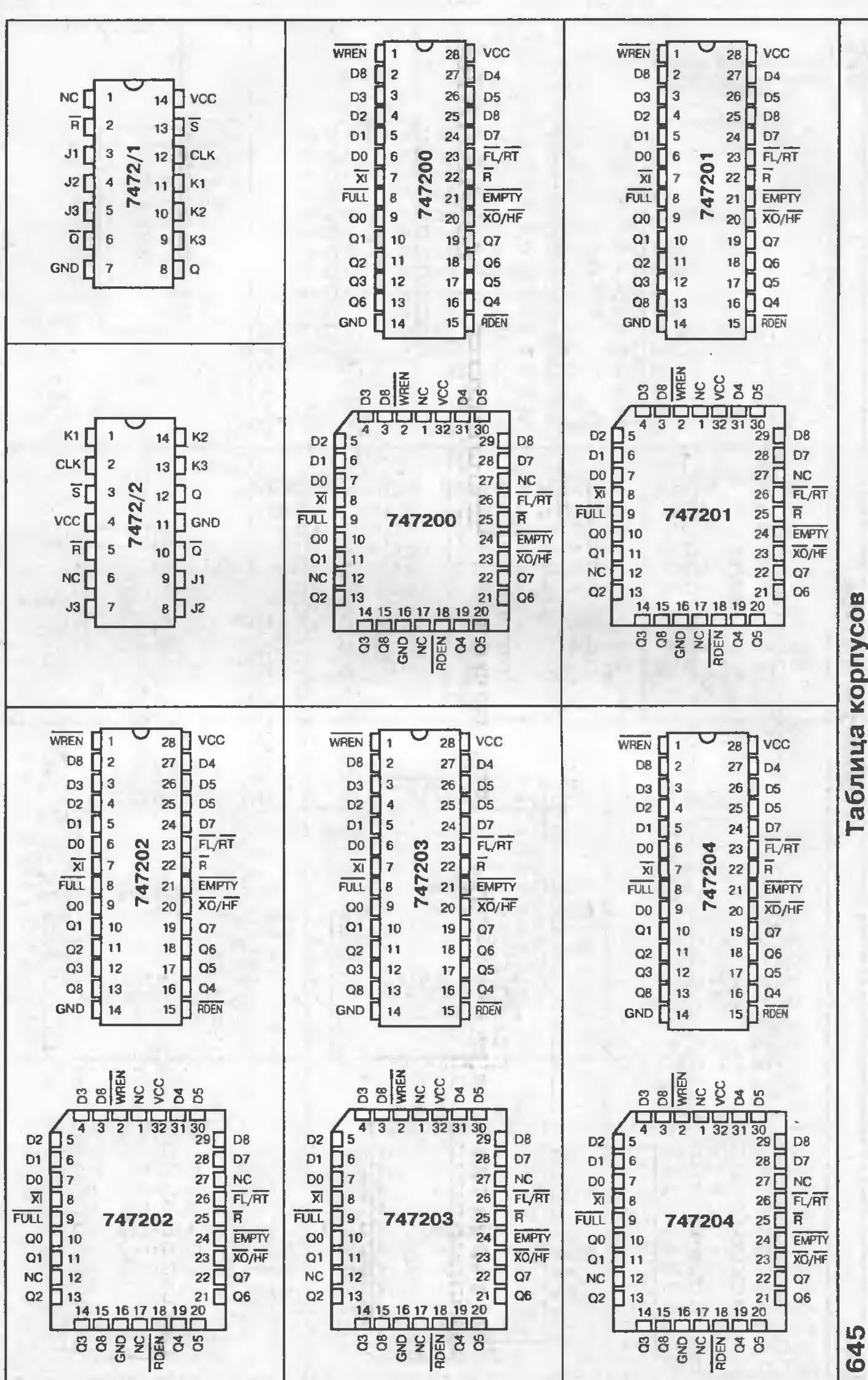
74691 (PLCC)

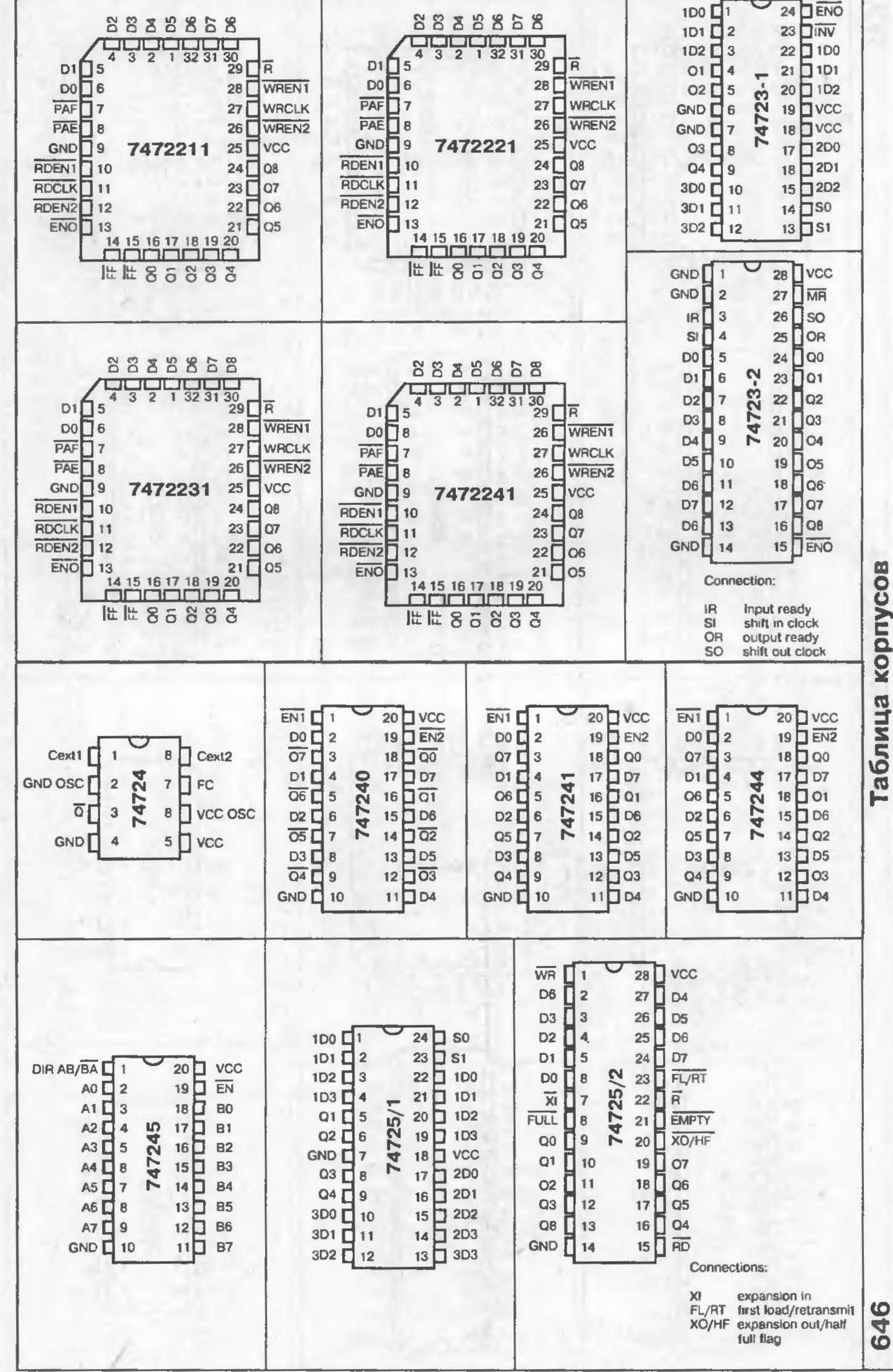
Pin	Signal	Pin	Signal	Pin	Signal	Pin	Signal
3	D0	4	D1	9	RCLK	18	Q0
2	CCLK	5	D2	10	GND	17	Q1
1	$\overline{CCLR}$	8	D3	11	$R/\overline{C}$	16	Q2
20	VCC	7	CEP	12	$\overline{EN}$	15	Q3
19	RCYO	8	$\overline{RCLR}$	13	$\overline{LOAD}$	14	CET

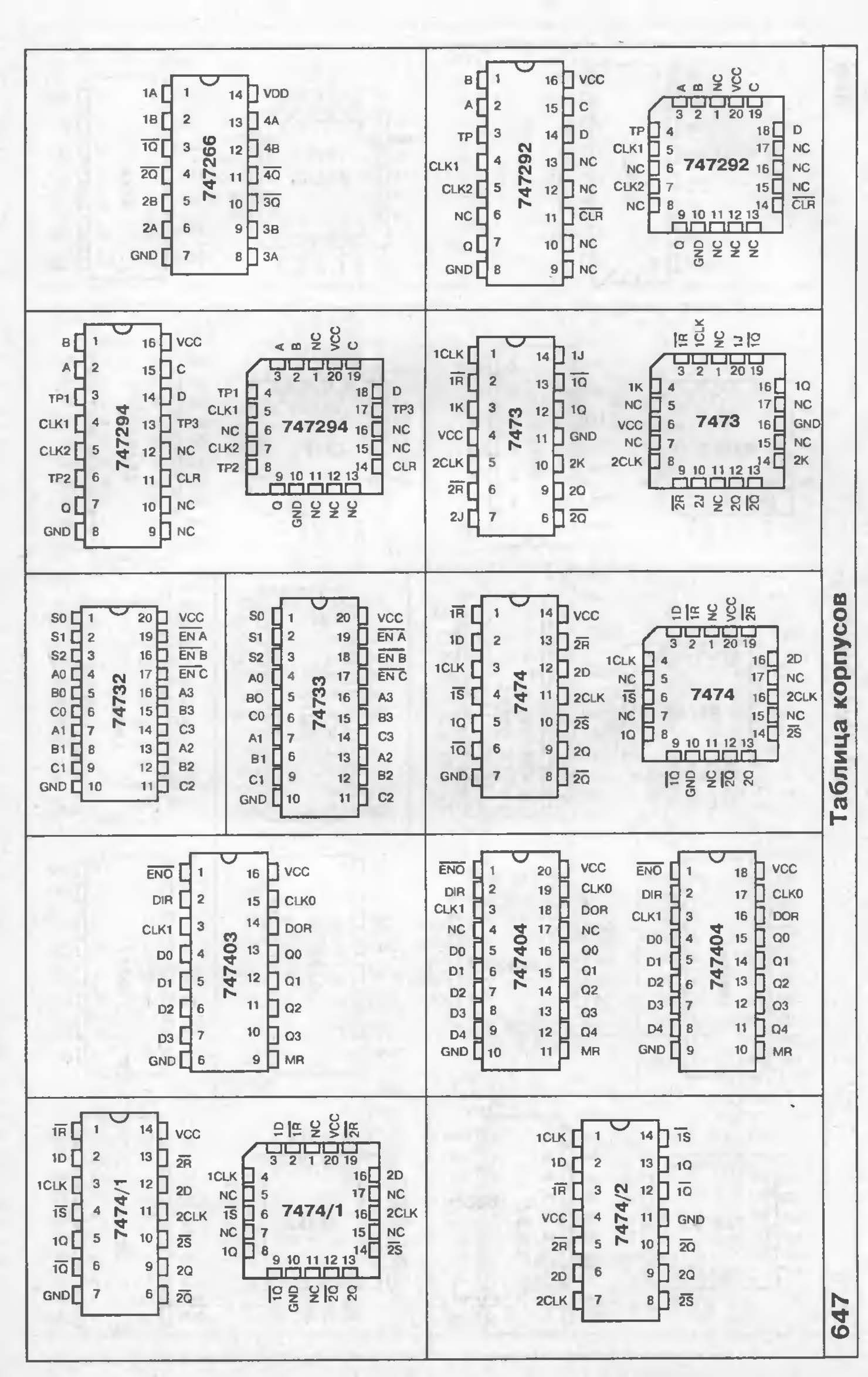

74692
CCLR 1 20 VCC
CCLK 2 19 RCYO
D0 3 18 Q0
D1 4 17 Q1
D2 5 16 Q2
D3 6 15 Q3
CEN 7 14 CET
RCLR 8 13 LOAD
RCLK 9 12 EN
GND 10 11 R/C
74692
74693
CCLR 1 20 VCC
CCLK 2 19 RCYO
D0 3 18 Q0
D1 4 17 Q1
D2 5 16 Q2
D3 6 15 Q3
CEN 7 14 CET
RCLR 8 13 LOAD
RCLK 9 12 EN
GND 10 11 R/C
74693
74696
U/D 1 20 VCC
CCLK 2 19 RCYO
D0 3 18 Q0
D1 4 17 Q1
D2 5 16 Q2
D3 8 15 Q3
CEN 7 14 CET
RCLR 8 13 LOAD
RCLK 9 12 EN
GND 10 11 R/C
74696
74697
U/D 1 20 VCC
CCLK 2 19 RCYO
D0 3 18 Q0
D1 4 17 Q1
D2 5 16 Q2
D3 6 15 Q3
CEN 7 14 CET
RCLR 8 13 LOAD
RCLK 9 12 EN
GND 10 11 R/C
74697
74698
U/D 1 20 VCC
CCLK 2 19 RCYO
D0 3 18 O0
D1 4 17 Q1
D2 5 16 Q2
D3 6 15 Q3
CEN 7 14 CET
RCLR 8 13 LOAD
RCLK 9 12 EN
GND 10 11 R/C
74696
74699
U/D 1 20 VCC
CCLK 2 19 RCYO
D0 3 18 Q0
D1 4 17 Q1
D2 5 16 Q2
D3 6 15 Q3
CEN 7 14 CET
RCLR 8 13 LOAD
RCLK 9 12 EN
GND 10 11 R/C
74699
747001
1B 1 14 VCC
1A 2 13 4B
1Q 3 12 4A
2B 4 11 4Q
2A 5 10 3B
2Q 8 9 3A
GND 7 8 3Q
747001
747002
1B 1 14 VCC
1A 2 13 4B
1Q 3 12 4A
2B 4 11 4Q
2A 5 10 3B
2Q 6 9 3A
GND 7 8 3Q
747002
747006
1A 1 24 VCC
1B 2 23 2A
1Q 3 22 2B
1C 4 21 2Q
1D 5 20 2C
3A 6 19 2D
3B 7 18 4A
3C 8 17 4B
3Q 9 18 4C
5Q 10 15 4Q
6A 11 14 6Q
GND 12 13 6A
747006
747007
1A 1 14 VCC
1Q 2 13 6A
2A 3 12 6Q
2Q 4 11 5A
3A 5 10 5Q
3Q 6 9 4A
GND 7 8 4Q
747007

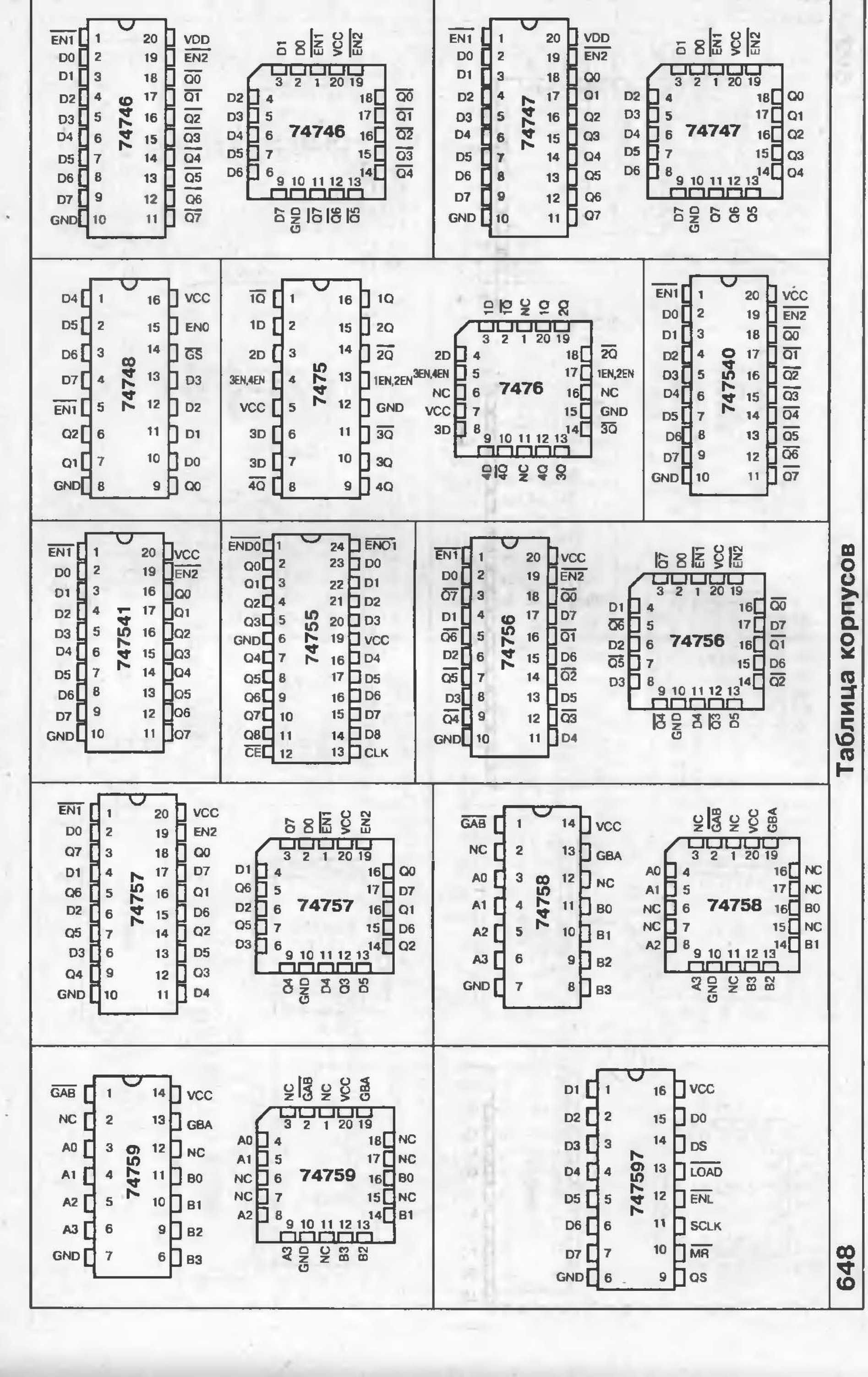

747008
1A 1 24 VCC
1B 2 23 4A
1Q 3 22 4B
2Q 4 21 4Q
2A 5 20 5Q
2B 6 19 5A
3A 7 18 5B
3B 8 17 6A
3Q 9 16 6B
7Q 10 15 6Q
7A 11 14 6Q
GND 12 13 6A
747008
1Q 1B 1A NC VCC 4A 4B
4 3 2 1 28 27 26
2Q 5 25 4Q
2A 6 24 5Q
2B 7 23 5A
NC 8 22 NC
3A 9 21 5B
3B 10 20 6A
3Q 11 19 6B
12 13 14 15 16 17 18
7Q 7A GND NC 8A 8Q 6Q
7470-1
NC 1 14 VCC
R 2 13 S
J1 3 12 CLK
J2 4 11 K1
J 5 10 K2
Q 6 9 K
GND 7 8 Q
74701
CET 1 24 TC
CCLR 2 23 D0
RCLR 3 22 D1
CLK 4 21 D2
SEL 5 20 D3
GND 6 19 VCC
GND 7 18 VCC
ENO 8 17 D4
S2 9 16 D5
S1 10 15 D6
S0 11 14 D7
ENL 12 13 A=B
7470-2
K1 1 14 K2
CLK 2 13 K
S 3 12 Q
VCC 4 11 GND
R 5 10 Q
NC 6 9 J
J1 7 8 J2
74702
SEL BA 1 24 ENL B
A0 2 23 ENO B
A1 3 22 B0
A2 4 21 B1
A3 5 20 B2
VCC 6 19 B3
A4 7 18 GND
A5 8 17 B4
A6 9 16 B5
A7 10 15 B6
END A 11 14 B7
ENL A 12 13 SEL AB
747022
Q1 1 16 VCC
Q0 2 15 CLR
Q2 3 14 CLK
Q5 4 13 CLKEN
Q6 5 12 CYO
Cext 6 11 Q4
Q3 7 10 Q7
GND 8 9 CLR DUT
747022
Q0 Q1 NC VCC CLR
3 2 1 20 19
Q2 4 18 CLK
Q5 5 17 CLKEN
NC 6 16 NC
Q6 7 15 CYO
Cext 8 14 Q4
9 10 11 12 13
Q3 GND NC CLR OUT Q7
747030
GND 1 28 VCC
GND 2 27 MR
DIR 3 26 SO
SI 4 25 DOR
D0 5 24 Q0
D1 6 23 Q1
D2 7 22 Q2
D3 8 21 Q3
D4 9 20 Q4
D5 10 19 Q5
D6 11 18 Q6
D7 12 17 Q7
D8 13 16 Q8
GND 14 15 ENO
Connection:
SI shift in
DIR data-in ready
SO shift out
DOR data-out ready
747032
1A 1 14 VCC
1B 2 13 4B
1Q 3 12 4A
2A 4 11 4Q
2B 5 10 3B
2Q 6 9 3A
GND 7 8 3Q
747032
1B 1A NC VCC 4B
3 2 1 20 19
1Q 4 18 4A
NC 5 17 NC
2A 6 16 4Q
NC 7 15 NC
2B 8 14 3B
9 10 11 12 13
2Q GND NC 3Q 3A
747038
GAB 1 24 VCC
ENL 2 23 GBA
A0 3 22 B0
A1 4 21 B1
A2 5 20 B2
A3 6 19 B3
A4 7 18 B4
A5 8 17 B5
A6 9 16 B6
A7 10 15 B7
A8 11 14 B8
GND 12 13 POL
747046
LD 1 16 VCC
PC1 2 15 CLD
COMP IN 3 14 SIG IN
VCO OUT 4 13 PC2
INH 5 12 Rext2
Cext1 6 11 Rext1
Cext2 7 10 DEM OUT
GND 8 9 VCO IN
747060
QI 1 20 VCC
QH 2 19 QJ
QG 3 18 QK
QF 4 17 QL
QE 5 16 QM
QD 6 15 QN
QC 7 14 CLR
QB 8 13 CKO
QA 9 12 CKO
GND 10 11 CKI
747061
QI 1 20 VCC
QH 2 19 QJ
QG 3 18 QK
QF 4 17 QL
QE 5 16 QM
QD 6 15 QN
QC 7 14 CLR
QB 8 13 CKD
QA 9 12 CKO
GND 10 11 CKI

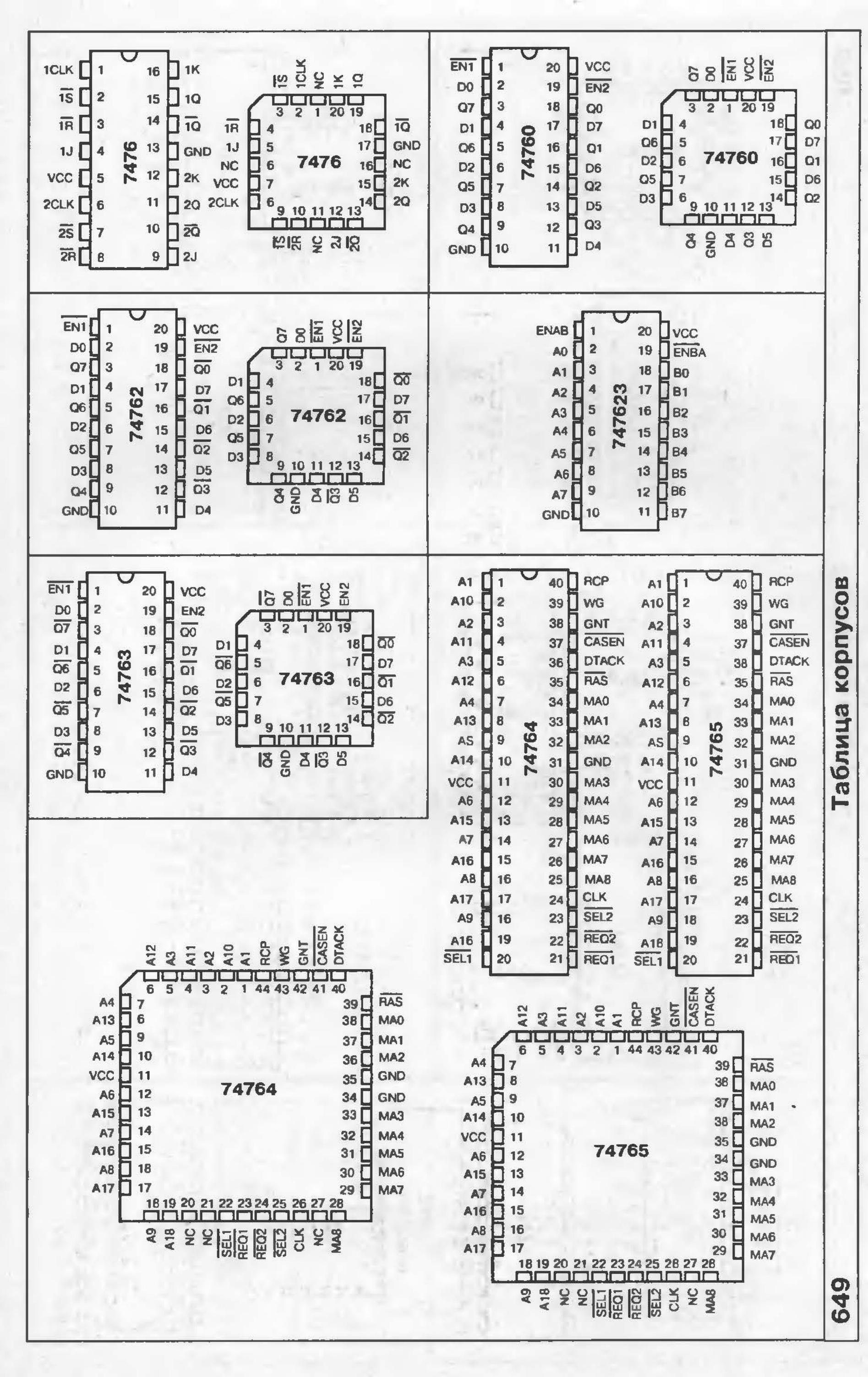

747074
1A 1 24 VCC
2Q 2 23 1Q
3A 3 22 2A
3B 4 21 6B
3Q 5 20 6A
4CLK 6 19 6Q
4S 7 16 5CLK
4D 8 17 5S
4Q 9 16 5D
4R 10 15 5Q
4Q 11 14 5R
GND 12 13 5Q
747075
1A 1 24 VCC
2Q 2 23 1Q
3A 3 22 2A
3B 4 21 6B
3Q 5 20 6A
4CLK 6 19 6Q
4S 7 18 5CLK
4D 8 17 5S
4Q 9 16 5D
4R 10 15 5Q
4Q 11 14 5R
GND 12 13 5Q
747076
1A 1 24 VCC
2Q 2 23 1Q
3A 3 22 2A
3B 4 21 6B
3Q 5 20 6A
4CLK 6 19 6Q
4S 7 18 5CLK
4D 8 17 5S
4Q 9 16 5D
4R 10 15 5Q
4Q 11 14 5R
GND 12 13 5Q
747074
3A 2Q 1A NC VCC 1Q 2A
4 3 2 1 28 27 26
3B 5 25 6B
3Q 8 24 6A
4CLK 7 23 6Q
NC 8 22 NC
4S 9 21 5CLK
4D 10 20 5S
4Q 11 19 5D
12 13 14 15 16 17 18
4R 4Q GND NC 5Q 6Q 5Q
747075
3A 2Q 1A NC VCC 1Q 2A
4 3 2 1 28 27 26
3B 5 25 6B
3Q 8 24 6A
4CLK 7 23 6Q
NC 8 22 NC
4S 9 21 5CLK
4D 10 20 5S
4Q 11 19 5D
12 13 14 15 18 17 18
4R 4Q GND NC 5Q 6Q 5Q
747076
3A 2Q 1A NC VCC 1Q 2A
4 3 2 1 28 27 26
3B 5 25 6B
3Q 6 24 6A
4CLK 7 23 6Q
NC 8 22 NC
4S 9 21 5CLK
4D 10 20 5S
4Q 11 19 5D
12 13 14 15 18 17 18
4R 4Q GND NC 5Q 6Q 5Q
74708
FULL 1 26 VCC
HF 2 27 MR
IR 3 26 SO
SI 4 25 OR
D0 5 24 Q0
D1 6 23 Q1
D2 7 22 Q2
D3 8 21 Q3
D4 9 20 Q4
D5 10 19 Q5
D6 11 18 Q6
D7 12 17 Q7
D6 13 16 Q6
GND 14 15 ENO
747080
CASCI 1 20 VCC
D0 2 19 OE/QO
D1 3 18 D15
D2 4 17 D14
D3 5 16 D13
D4 6 15 D12
D5 7 14 D11
D6 8 13 D10
D7 9 12 D9
GND 10 11 D6
7471/1
J1 1 14 VCC
J2 2 13 CLK
J3 3 12 K1
J4 4 11 K2
S 5 10 K3
Q 6 9 K4
GND 7 6 Q
7471/2
K3 1 14 K1
K4 2 13 K2
CLK 3 12 Q
VCC 4 11 GND
J1 5 10 Q
J2 6 9 S
J3 7 8 J4
Connection:
IR Input ready
SI shift in clock
OR output ready
SO shift out clock
7471/3
NC 1 14 VCC
CLR 2 13 SET
J1 3 12 CLK
J2 4 11 K1
J3 5 10 K2
Q 6 9 K3
GND 7 8 Q
7471/4
K1 1 14 K2
CLK 2 13 K3
S 3 12 Q
VCC 4 11 GND
R 5 10 Q
NC 6 9 J1
J3 7 8 J2
74711
1D0 1 20 1D1
2D0 2 19 2D1
1Q 3 18 1D2
2Q 4 17 2D2
GND 5 16 VCC
3Q 6 15 1D3
4Q 7 14 2D3
5Q 8 13 1D4
S 9 12 2D4
INV 10 11 ENO
74712
S0 1 24 1D0
S1 2 23 1D1
Q1 3 22 1D2
Q2 4 21 1D3
Q3 5 20 1D4
GND 6 19 VCC
Q4 7 18 2D0
Q5 8 17 2D1
3D0 9 16 2D2
3D1 10 15 2D3
3D2 11 14 2D4
3D3 12 13 3D4
74716
Q3 1 16 VCC
D3 2 15 Q2
ENP 3 14 D2
GATE 4 13 R
D0 5 12 CYD
CLK 6 11 D1
Q0 7 10 MR
GND 8 9 Q1
74718
Q3 1 16 VCC
D3 2 15 Q2
ENP 3 14 D2
GATE 4 13 R
D0 5 12 CYD
CLK 6 11 D1
Q0 7 10 MR
GND 8 9 Q1

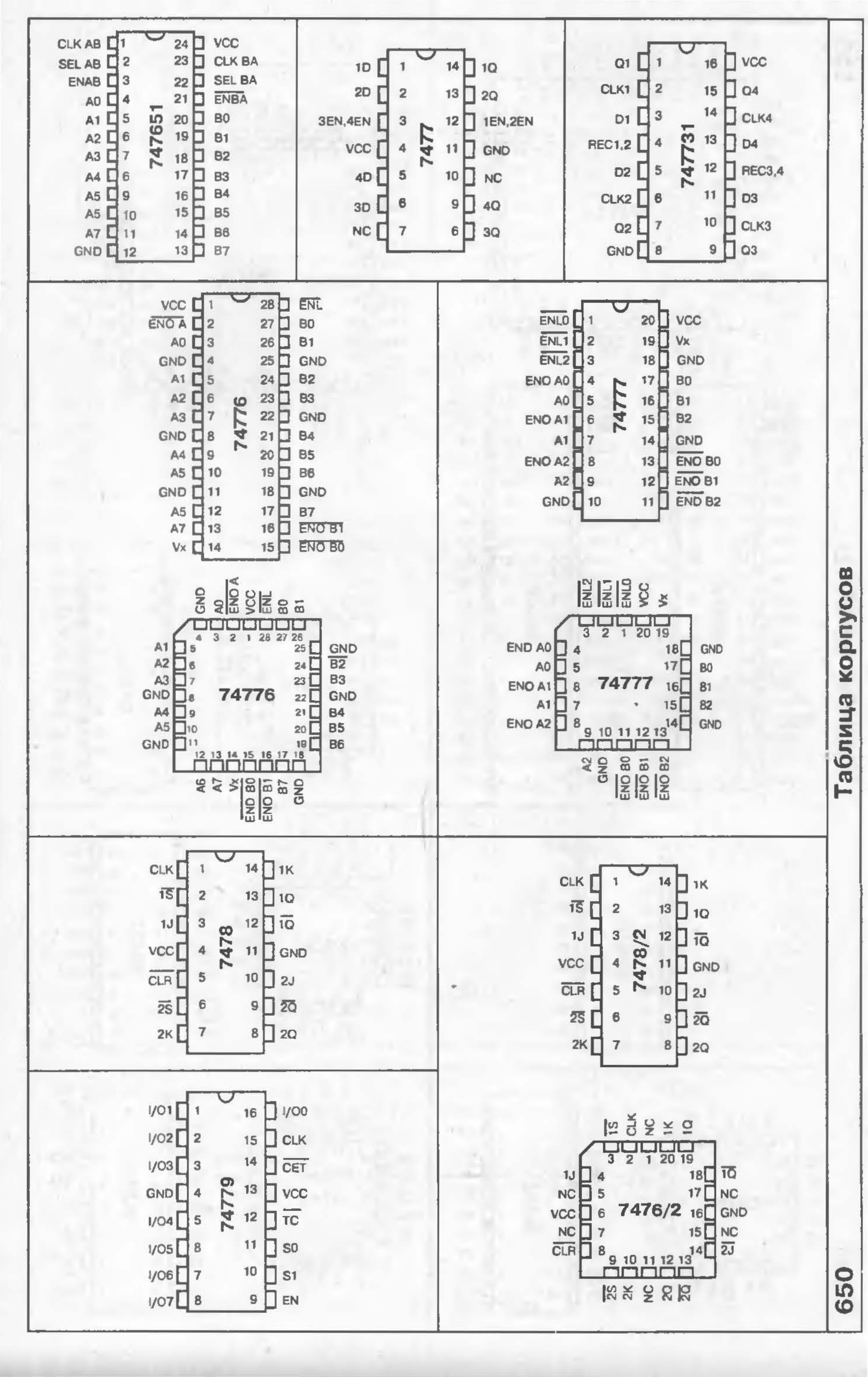

7472/1
7472/2
747200
747200
747201
747201
747202
747202
747203
747203
747204
747204

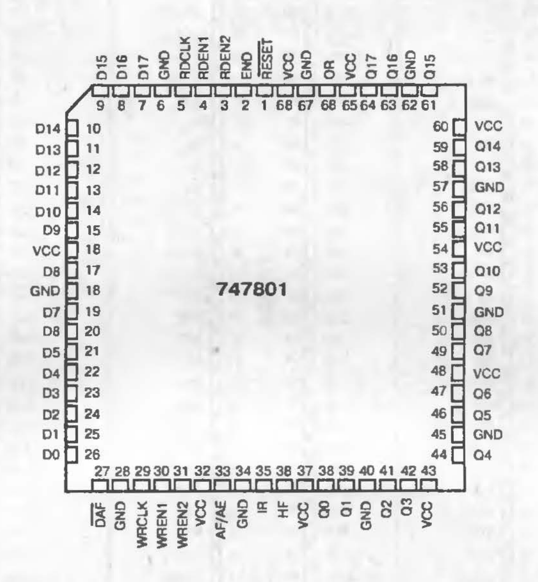

7472211
D2 D3 D4 D5 D6 D7 D8
D1 D0 PAF PAE GND RDEN1 RDCLK RDEN2 ENO
R WREN1 WRCLK WREN2 VCC Q8 Q7 Q6 Q5
FF FF Q0 Q1 Q2 Q3 Q4
7472221
D2 D3 D4 D5 D6 D7 D8
D1 D0 PAF PAE GND RDEN1 RDCLK RDEN2 ENO
R WREN1 WRCLK WREN2 VCC Q8 Q7 Q6 Q5
FF FF Q0 Q1 Q2 Q3 Q4
74723-1
1D0 1D1 1D2 O1 O2 GND GND O3 Q4 3D0 3D1 3D2
ENO INV 1D0 1D1 1D2 VCC VCC 2D0 2D1 2D2 S0 S1
7472231
D2 D3 D4 D5 D6 D7 D8
D1 D0 PAF PAE GND RDEN1 RDCLK RDEN2 ENO
R WREN1 WRCLK WREN2 VCC Q8 Q7 Q6 Q5
FF FF Q0 Q1 Q2 Q3 Q4
7472241
D2 D3 D4 D5 D6 D7 D8
D1 D0 PAF PAE GND RDEN1 RDCLK RDEN2 ENO
R WREN1 WRCLK WREN2 VCC Q8 Q7 Q6 O5
FF FF Q0 Q1 Q2 Q3 Q4
74723-2
GND GND IR SI D0 D1 D2 D3 D4 D5 D6 D7 D8 GND
VCC MR SO OR Q0 Q1 Q2 Q3 O4 O5 Q6 Q7 Q8 ENO
Connection:
IR input ready
SI shift in clock
OR output ready
SO shift out clock
74724
Cext1 GND OSC Q GND
Cext2 FC VCC OSC VCC
747240
EN1 D0 O7 D1 Q6 D2 O5 D3 Q4 GND
VCC EN2 Q0 D7 Q1 D6 Q2 D5 O3 D4
747241
EN1 D0 Q7 D1 Q6 D2 Q5 D3 Q4 GND
VCC EN2 Q0 D7 Q1 D6 O2 D5 Q3 D4
747244
EN1 D0 Q7 D1 Q6 D2 Q5 D3 Q4 GND
VCC EN2 Q0 D7 O1 D6 Q2 D5 O3 D4
747245
DIR AB/BA A0 A1 A2 A3 A4 A5 A6 A7 GND
VCC EN B0 B1 B2 B3 B4 B5 B6 B7
74725/1
1D0 1D1 1D2 1D3 Q1 Q2 GND Q3 Q4 3D0 3D1 3D2
S0 S1 1D0 1D1 1D2 1D3 VCC 2D0 2D1 2D2 2D3 3D3
74725/2
WR D6 D3 D2 D1 D0 XI FULL Q0 Q1 O2 Q3 Q8 GND
VCC D4 D5 D6 D7 FL/RT R EMPTY XO/HF O7 Q6 Q5 Q4 RD
Connections:
XI expansion in
FL/RT first load/retransmit
XO/HF expansion out/half full flag

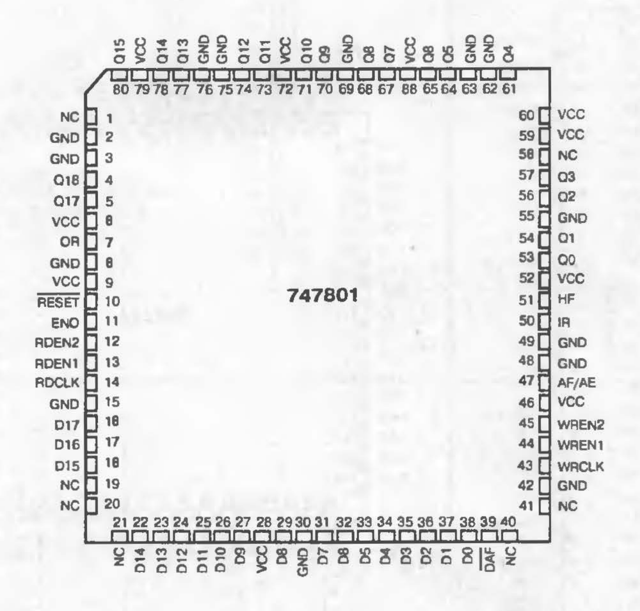

747266
1A 1 — 14 VDD
1B 2 — 13 4A
$\overline{1Q}$ 3 — 12 4B
$\overline{2Q}$ 4 — 11 $\overline{4Q}$
2B 5 — 10 $\overline{3Q}$
2A 6 — 9 3B
GND 7 — 8 3A
747292
B 1 — 16 VCC
A 2 — 15 C
TP 3 — 14 D
CLK1 4 — 13 NC
CLK2 5 — 12 NC
NC 6 — 11 $\overline{CLR}$
Q 7 — 10 NC
GND 8 — 9 NC
747292
A 3, B 2, NC 1, VCC 20, C 19
TP 4, CLK1 5, NC 6, CLK2 7, NC 8
18 D, 17 NC, 16 NC, 15 NC, 14 $\overline{CLR}$
9 Q, 10 GND, 11 NC, 12 NC, 13 NC
747294
B 1 — 16 VCC
A 2 — 15 C
TP1 3 — 14 D
CLK1 4 — 13 TP3
CLK2 5 — 12 NC
TP2 6 — 11 CLR
Q 7 — 10 NC
GND 8 — 9 NC
747294
A 3, B 2, NC 1, VCC 20, C 19
TP1 4, CLK1 5, NC 6, CLK2 7, TP2 8
18 D, 17 TP3, 16 NC, 15 NC, 14 CLR
9 Q, 10 GND, 11 NC, 12 NC, 13 NC
7473
1CLK 1 — 14 1J
$\overline{1R}$ 2 — 13 $\overline{1Q}$
1K 3 — 12 1Q
VCC 4 — 11 GND
2CLK 5 — 10 2K
$\overline{2R}$ 6 — 9 2Q
2J 7 — 6 $\overline{2Q}$
7473
$\overline{1R}$ 3, 1CLK 2, NC 1, 1J 20, $\overline{1Q}$ 19
1K 4, NC 5, VCC 6, NC 7, 2CLK 8
16 1Q, 17 NC, 16 GND, 15 NC, 14 2K
9 $\overline{2R}$, 10 2J, 11 NC, 12 2Q, 13 $\overline{2Q}$
74732
S0 1 — 20 VCC
S1 2 — 19 $\overline{EN\ A}$
S2 3 — 16 $\overline{EN\ B}$
A0 4 — 17 $\overline{EN\ C}$
B0 5 — 16 A3
C0 6 — 15 B3
A1 7 — 14 C3
B1 8 — 13 A2
C1 9 — 12 B2
GND 10 — 11 C2
74733
S0 1 — 20 VCC
S1 2 — 19 $\overline{EN\ A}$
S2 3 — 18 $\overline{EN\ B}$
A0 4 — 17 $\overline{EN\ C}$
BO 5 — 16 A3
C0 6 — 15 B3
A1 7 — 14 C3
B1 6 — 13 A2
C1 9 — 12 B2
GND 10 — 11 C2
7474
$\overline{1R}$ 1 — 14 VCC
1D 2 — 13 $\overline{2R}$
1CLK 3 — 12 2D
$\overline{1S}$ 4 — 11 2CLK
1Q 5 — 10 $\overline{2S}$
$\overline{1Q}$ 6 — 9 2Q
GND 7 — 8 $\overline{2Q}$
7474
1D 3, $\overline{1R}$ 2, NC 1, VCC 20, $\overline{2R}$ 19
1CLK 4, NC 5, $\overline{1S}$ 6, NC 7, 1Q 8
16 2D, 17 NC, 16 2CLK, 15 NC, 14 $\overline{2S}$
9 $\overline{1Q}$, 10 GND, 11 NC, 12 $\overline{2Q}$, 13 2Q
747403
$\overline{ENO}$ 1 — 16 VCC
DIR 2 — 15 CLK0
CLK1 3 — 14 DOR
D0 4 — 13 Q0
D1 5 — 12 Q1
D2 6 — 11 Q2
D3 7 — 10 Q3
GND 6 — 9 MR
747404
$\overline{ENO}$ 1 — 20 VCC
DIR 2 — 19 CLK0
CLK1 3 — 18 DOR
NC 4 — 17 NC
D0 5 — 16 Q0
D1 6 — 15 Q1
D2 7 — 14 Q2
D3 8 — 13 Q3
D4 9 — 12 Q4
GND 10 — 11 MR
747404
$\overline{ENO}$ 1 — 18 VCC
DIR 2 — 17 CLK0
CLK1 3 — 16 DOR
D0 4 — 15 Q0
D1 5 — 14 Q1
D2 6 — 13 Q2
D3 7 — 12 Q3
D4 8 — 11 Q4
GND 9 — 10 MR
7474/1
$\overline{1R}$ 1 — 14 VCC
1D 2 — 13 $\overline{2R}$
1CLK 3 — 12 2D
$\overline{1S}$ 4 — 11 2CLK
1Q 5 — 10 $\overline{2S}$
$\overline{1Q}$ 6 — 9 2Q
GND 7 — 6 $\overline{2Q}$
7474/1
1D 3, $\overline{1R}$ 2, NC 1, VCC 20, $\overline{2R}$ 19
1CLK 4, NC 5, $\overline{1S}$ 6, NC 7, 1Q 8
16 2D, 17 NC, 16 2CLK, 15 NC, 14 $\overline{2S}$
9 $\overline{1Q}$, 10 GND, 11 NC, 12 $\overline{2Q}$, 13 2Q
7474/2
1CLK 1 — 14 $\overline{1S}$
1D 2 — 13 1Q
$\overline{1R}$ 3 — 12 $\overline{1Q}$
VCC 4 — 11 GND
$\overline{2R}$ 5 — 10 $\overline{2Q}$
2D 6 — 9 2Q
2CLK 7 — 8 $\overline{2S}$


74746
74747
74748
7475
7476
747540
747541
74755
74756
74757
74758
74759
747597


7476
1CLK 1 16 1K
1S 2 15 1Q
1R 3 14 1Q
1J 4 13 GND
VCC 5 12 2K
2CLK 6 11 2Q
2S 7 10 2Q
2R 8 9 2J
7476
1S 3, 1CLK 2, NC 1, 1K 20, 1Q 19
1R 4, 1J 5, NC 6, VCC 7, 2CLK 6
18 1Q, 17 GND, 16 NC, 15 2K, 14 2Q
9 2S, 10 2R, 11 NC, 12 2J, 13 2Q
74760
EN1 1 20 VCC
D0 2 19 EN2
Q7 3 18 Q0
D1 4 17 D7
Q6 5 16 Q1
D2 6 15 D6
Q5 7 14 Q2
D3 8 13 D5
Q4 9 12 Q3
GND 10 11 D4
74760
Q7 3, D0 2, EN1 1, VCC 20, EN2 19
D1 4, Q6 5, D2 6, Q5 7, D3 6
18 Q0, 17 D7, 16 Q1, 15 D6, 14 Q2
9 Q4, 10 GND, 11 D4, 12 Q3, 13 D5
74762
EN1 1 20 VCC
D0 2 19 EN2
Q7 3 18 Q0
D1 4 17 D7
Q6 5 16 Q1
D2 6 15 D6
Q5 7 14 Q2
D3 8 13 D5
Q4 9 12 Q3
GND 10 11 D4
74762
Q7 3, D0 2, EN1 1, VCC 20, EN2 19
D1 4, Q6 5, D2 6, Q5 7, D3 8
18 Q0, 17 D7, 16 Q1, 15 D6, 14 Q2
9 Q4, 10 GND, 11 D4, 12 Q3, 13 D5
747623
ENAB 1 20 VCC
A0 2 19 ENBA
A1 3 18 B0
A2 4 17 B1
A3 5 16 B2
A4 6 15 B3
A5 7 14 B4
A6 8 13 B5
A7 9 12 B6
GND 10 11 B7
74763
EN1 1 20 VCC
D0 2 19 EN2
Q7 3 18 Q0
D1 4 17 D7
Q6 5 16 Q1
D2 6 15 D6
Q5 7 14 Q2
D3 8 13 D5
Q4 9 12 Q3
GND 10 11 D4
74763
Q7 3, D0 2, EN1 1, VCC 20, EN2 19
D1 4, Q6 5, D2 6, Q5 7, D3 8
18 Q0, 17 D7, 16 Q1, 15 D6, 14 Q2
9 Q4, 10 GND, 11 D4, 12 Q3, 13 D5
74764
A1 1 40 RCP
A10 2 39 WG
A2 3 38 GNT
A11 4 37 CASEN
A3 5 36 DTACK
A12 6 35 RAS
A4 7 34 MA0
A13 8 33 MA1
AS 9 32 MA2
A14 10 31 GND
VCC 11 30 MA3
A6 12 29 MA4
A15 13 28 MA5
A7 14 27 MA6
A16 15 26 MA7
A8 16 25 MA8
A17 17 24 CLK
A9 16 23 SEL2
A16 19 22 REQ2
SEL1 20 21 REQ1
74765
A1 1 40 RCP
A10 2 39 WG
A2 3 38 GNT
A11 4 37 CASEN
A3 5 38 DTACK
A12 6 35 RAS
A4 7 34 MA0
A13 8 33 MA1
AS 9 32 MA2
A14 10 31 GND
VCC 11 30 MA3
A6 12 29 MA4
A15 13 28 MA5
A7 14 27 MA6
A16 15 26 MA7
A8 16 25 MA8
A17 17 24 CLK
A9 18 23 SEL2
A18 19 22 REQ2
SEL1 20 21 REQ1
74764
A12 6, A3 5, A11 4, A2 3, A10 2, A1 1, RCP 44, WG 43, GNT 42, CASEN 41, DTACK 40
A4 7, A13 6, A5 9, A14 10, VCC 11, A6 12, A15 13, A7 14, A16 15, A8 18, A17 17
39 RAS, 38 MA0, 37 MA1, 36 MA2, 35 GND, 34 GND, 33 MA3, 32 MA4, 31 MA5, 30 MA6, 29 MA7
18 A9, 19 A18, 20 NC, 21 NC, 22 SEL1, 23 REQ1, 24 REQ2, 25 SEL2, 26 CLK, 27 NC, 28 MA8
74765
A12 6, A3 5, A11 4, A2 3, A10 2, A1 1, RCP 44, WG 43, GNT 42, CASEN 41, DTACK 40
A4 7, A13 8, A5 9, A14 10, VCC 11, A6 12, A15 13, A7 14, A16 15, A8 16, A17 17
39 RAS, 38 MA0, 37 MA1, 38 MA2, 35 GND, 34 GND, 33 MA3, 32 MA4, 31 MA5, 30 MA6, 29 MA7
18 A9, 19 A18, 20 NC, 21 NC, 22 SEL1, 23 REQ1, 24 REQ2, 25 SEL2, 26 CLK, 27 NC, 28 MA8


747651
CLK AB 1, SEL AB 2, ENAB 3, A0 4, A1 5, A2 6, A3 7, A4 8, A5 9, A5 10, A7 11, GND 12
VCC 24, CLK BA 23, SEL BA 22, ENBA 21, B0 20, B1 19, B2 18, B3 17, B4 16, B5 15, B6 14, B7 13
7477
1D 1, 2D 2, 3EN,4EN 3, VCC 4, 4D 5, 3D 6, NC 7
1Q 14, 2Q 13, 1EN,2EN 12, GND 11, NC 10, 4Q 9, 3Q 8
747731
Q1 1, CLK1 2, D1 3, REC1,2 4, D2 5, CLK2 6, Q2 7, GND 8
VCC 16, Q4 15, CLK4 14, D4 13, REC3,4 12, D3 11, CLK3 10, Q3 9
74776
VCC 1, ENO A 2, A0 3, GND 4, A1 5, A2 6, A3 7, GND 8, A4 9, A5 10, GND 11, A5 12, A7 13, Vx 14
ENL 28, B0 27, B1 26, GND 25, B2 24, B3 23, GND 22, B4 21, B5 20, B6 19, GND 18, B7 17, ENO B1 16, ENO B0 15
74777
ENL0 1, ENL1 2, ENL2 3, ENO A0 4, A0 5, ENO A1 6, A1 7, ENO A2 8, A2 9, GND 10
VCC 20, Vx 19, GND 18, B0 17, B1 16, B2 15, GND 14, ENO B0 13, ENO B1 12, END B2 11
74776
GND 4, A0 3, ENO A 2, VCC 1, ENL 28, B0 27, B1 26
A1 5, A2 6, A3 7, GND 8, A4 9, A5 10, GND 11
GND 25, B2 24, B3 23, GND 22, B4 21, B5 20, B6 19
A6 12, A7 13, Vx 14, END B0 15, ENO B1 16, B7 17, GND 18
74777
ENL2 3, ENL1 2, ENL0 1, VCC 20, Vx 19
END A0 4, A0 5, ENO A1 6, A1 7, ENO A2 8
GND 18, B0 17, 81 16, 82 15, GND 14
A2 9, GND 10, ENO B0 11, ENO B1 12, ENO B2 13
7478
CLK 1, 1S 2, 1J 3, VCC 4, CLR 5, 2S 6, 2K 7
1K 14, 1Q 13, 1Q 12, GND 11, 2J 10, 2Q 9, 2Q 8
7478/2
CLK 1, 1S 2, 1J 3, VCC 4, CLR 5, 2S 6, 2K 7
1K 14, 1Q 13, 1Q 12, GND 11, 2J 10, 2Q 9, 2Q 8
74779
I/O1 1, I/O2 2, I/O3 3, GND 4, I/O4 5, I/O5 8, I/O6 7, I/O7 8
I/O0 16, CLK 15, CET 14, VCC 13, TC 12, S0 11, S1 10, EN 9
7476/2
1S 3, CLK 2, NC 1, 1K 20, 1Q 19
1J 4, NC 5, VCC 6, NC 7, CLR 8
1Q 18, NC 17, GND 16, NC 15, 2J 14
2S 9, 2K 10, NC 11, 2Q 12, 2Q 13


747801
D15 9
D16 8
D17 7
GND 6
RDCLK 5
RDEN1 4
RDEN2 3
END 2
RESET 1
VCC 68
GND 67
OR 68
VCC 65
Q17 64
Q16 63
GND 62
Q15 61
D14 10
D13 11
D12 12
D11 13
D10 14
D9 15
VCC 18
D8 17
GND 18
D7 19
D8 20
D5 21
D4 22
D3 23
D2 24
D1 25
D0 26
60 VCC
59 Q14
58 Q13
57 GND
56 Q12
55 Q11
54 VCC
53 Q10
52 Q9
51 GND
50 Q8
49 Q7
48 VCC
47 Q6
46 Q5
45 GND
44 Q4
27 DAF
28 GND
29 WRCLK
30 WREN1
31 WREN2
32 VCC
33 AF/AE
34 GND
35 IR
38 HF
37 VCC
38 Q0
39 Q1
40 GND
41 Q2
42 Q3
43 VCC


747801
Q15 80
VCC 79
Q14 78
Q13 77
GND 76
GND 75
Q12 74
Q11 73
VCC 72
Q10 71
Q9 70
GND 69
Q8 68
Q7 67
VCC 88
Q8 65
Q5 64
GND 63
GND 62
Q4 61
NC 1
GND 2
GND 3
Q18 4
Q17 5
VCC 8
OR 7
GND 8
VCC 9
RESET 10
ENO 11
RDEN2 12
RDEN1 13
RDCLK 14
GND 15
D17 18
D16 17
D15 18
NC 19
NC 20
60 VCC
59 VCC
58 NC
57 Q3
56 Q2
55 GND
54 Q1
53 Q0
52 VCC
51 HF
50 IR
49 GND
48 GND
47 AF/AE
46 VCC
45 WREN2
44 WREN1
43 WRCLK
42 GND
41 NC
21 NC
22 D14
23 D13
24 D12
25 D11
26 D10
27 D9
28 VCC
29 D8
30 GND
31 D7
32 D8
33 D5
34 D4
35 D3
36 D2
37 D1
38 D0
39 DAF
40 NC

747802

Pin	Name	Pin	Name
1	$\overline{\text{RESET}}$	35	FULL
2	ENO	36	HF
3	NC	37	VCC
4	NC	38	Q0
5	UNCK	39	Q1
6	GND	40	GND
7	D17	41	Q2
8	D16	42	Q3
9	D15	43	VCC
10	D14	44	Q4
11	D13	45	GND
12	D12	46	Q5
13	D11	47	Q6
14	D10	48	VCC
15	D9	49	Q7
18	VCC	50	Q8
17	D8	51	GND
18	GND	52	Q9
19	D7	53	Q10
20	D6	54	VCC
21	D5	55	Q11
22	D4	56	Q12
23	D3	57	GND
24	D2	58	Q13
25	D1	59	Q14
26	D0	60	VCC
27	$\overline{\text{DAF}}$	61	Q15
28	GND	62	GND
29	LDCK	63	Q16
30	NC	64	Q17
31	NC	65	VCC
32	VCC	66	EMPTY
33	AF/AE	67	GND
34	GND	68	VCC

747803

Name	Pin	Pin	Name
$\overline{\text{RESET}}$	1	56	$\overline{\text{ENO1}}$
D17	2	55	Q17
D16	3	54	Q16
D15	4	53	Q15
D14	5	52	GND
D13	6	51	Q14
D12	7	50	VCC
D11	8	49	Q13
D10	9	48	Q12
VCC	10	47	Q11
D9	11	46	Q10
D8	12	45	Q9
GND	13	44	GND
D7	14	43	Q8
D6	15	42	Q7
D5	16	41	Q6
D4	17	40	Q5
D3	18	39	VCC
D2	19	38	Q4
D1	20	37	Q3
D0	21	38	Q2
HF	22	35	GND
$\overline{\text{PEN}}$	23	34	Q1
AF/AE	24	33	Q0
WRCLK	25	32	RDCLK
$\overline{\text{WREN2}}$	26	31	$\overline{\text{RDEN}}$
WREN1	27	30	$\overline{\text{END2}}$
IR	28	29	OR

747804

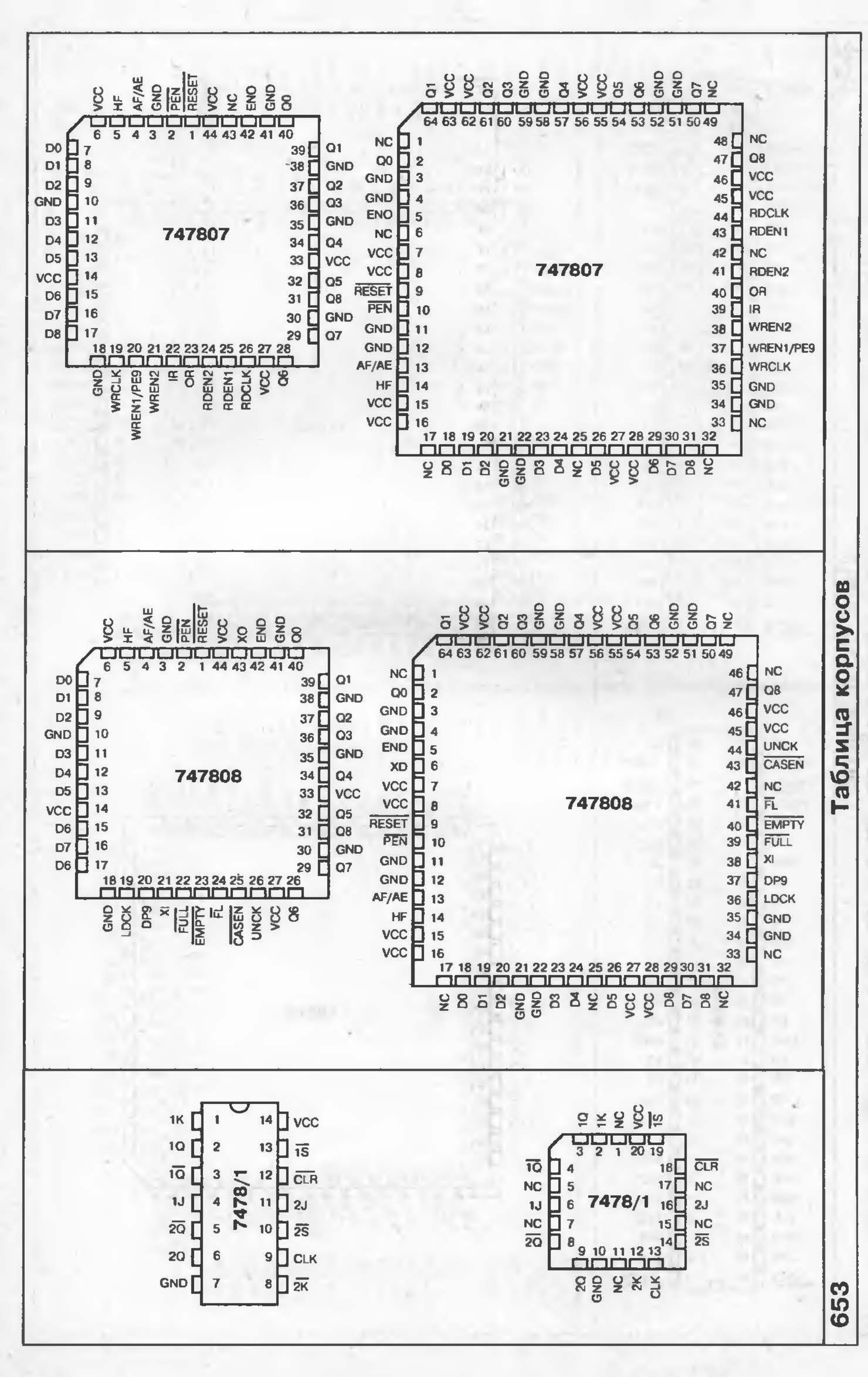
Name	Pin	Pin	Name
$\overline{\text{RESET}}$	1	56	$\overline{\text{ENO1}}$
D17	2	55	Q17
D16	3	54	Q16
D15	4	53	Q15
D14	5	52	GND
D13	6	51	Q14
D12	7	50	VCC
D11	8	49	Q13
D10	9	48	Q12
VCC	10	47	Q11
D9	11	46	Q10
D8	12	45	Q9
GND	13	44	GND
D7	14	43	Q8
D6	15	42	Q7
D5	16	41	Q8
D4	17	40	Q5
D3	18	39	VCC
D2	19	38	Q4
D1	20	37	Q3
D0	21	36	Q2
HF	22	35	GND
$\overline{\text{PEN}}$	23	34	Q1
AF/AE	24	33	Q0
LDCK	25	32	UNCK
NC	26	31	NC
NC	27	30	NC
$\overline{\text{FULL}}$	28	29	$\overline{\text{EMPTY}}$

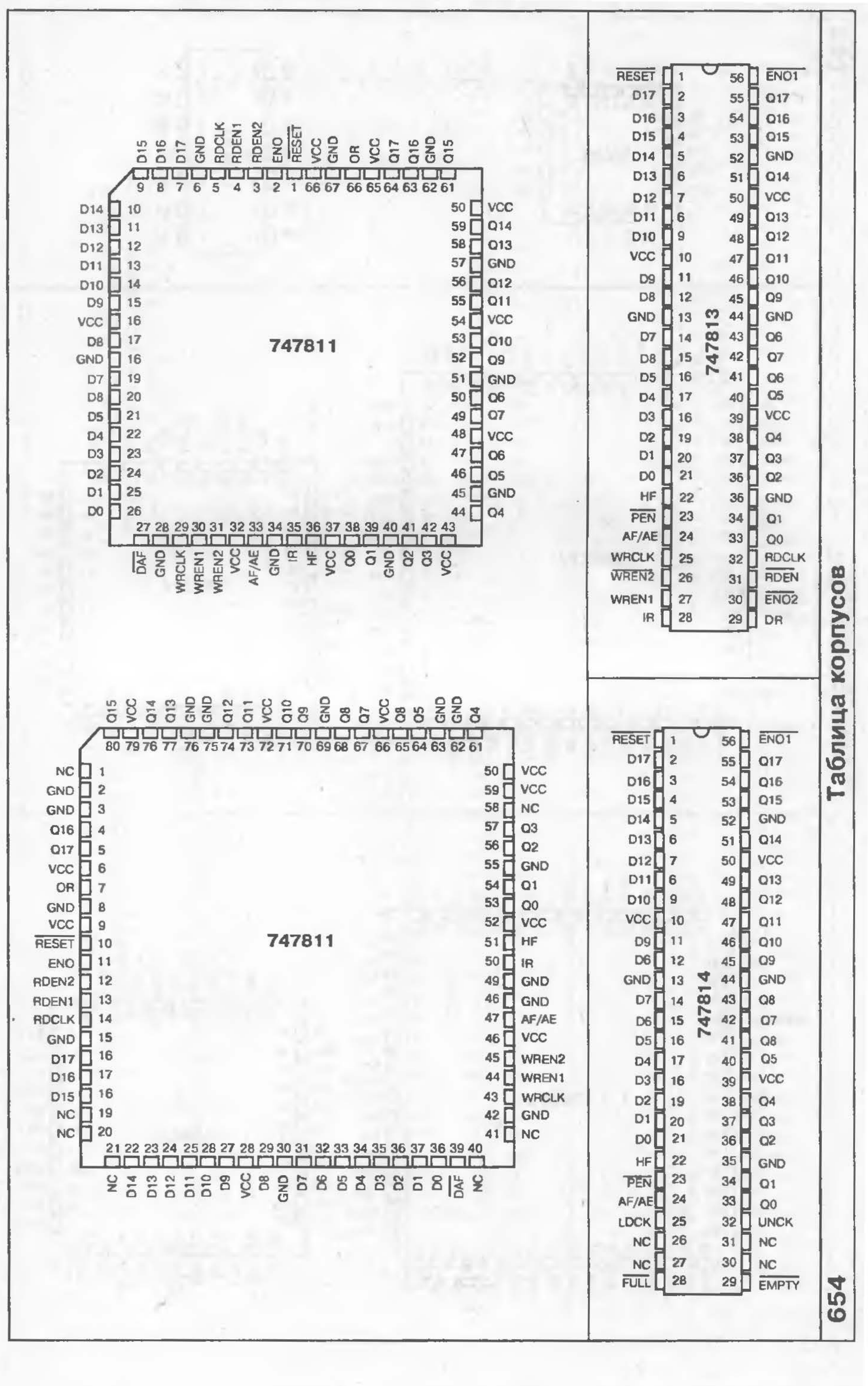
747805

Name	Pin	Pin	Name
$\overline{\text{RESET}}$	1	56	$\overline{\text{ENO1}}$
D17	2	55	Q17
D16	3	54	Q16
D15	4	53	Q15
D14	5	52	GND
D13	6	51	Q14
D12	7	50	VCC
D11	8	49	Q13
D10	9	48	Q12
VCC	10	47	Q11
D9	11	46	Q10
D8	12	45	Q9
GND	13	44	GND
D7	14	43	Q8
D6	15	42	Q7
D5	16	41	Q6
D4	17	40	Q5
D3	18	39	VCC
D2	19	38	Q4
D1	20	37	Q3
D0	21	36	Q2
HF	22	35	GND
$\overline{\text{PEN}}$	23	34	Q1
AF/AE	24	33	Q0
WRCLK	25	32	RDCLK
$\overline{\text{WREN2}}$	26	31	$\overline{\text{RDEN}}$
WREN1	27	30	$\overline{\text{ENO2}}$
IR	28	29	OR

747806

Name	Pin	Pin	Name
$\overline{\text{RESET}}$	1	56	$\overline{\text{ENO1}}$
D17	2	55	Q17
D16	3	54	Q16
D15	4	53	Q15
D14	5	52	GND
D13	6	51	Q14
D12	7	50	VCC
D11	8	49	Q13
D10	9	48	Q12
VCC	10	47	Q11
D9	11	46	Q10
D9	12	45	Q9
GND	13	44	GND
D7	14	43	Q6
D6	15	42	Q7
D5	18	41	Q6
D4	17	40	Q5
D3	18	39	VCC
D2	19	38	Q4
D1	20	37	Q3
D0	21	36	Q2
HF	22	35	GND
$\overline{\text{PEN}}$	23	34	Q1
AF/AE	24	33	Q0
LDCK	25	32	UNCK
NC	26	31	NC
NC	27	30	NC
$\overline{\text{FULL}}$	28	29	$\overline{\text{EMPTY}}$


747807
VCC HF AF/AE GND PEN RESET VCC NC ENO GND Q0
6 5 4 3 2 1 44 43 42 41 40
D0 7
D1 8
D2 9
GND 10
D3 11
D4 12
D5 13
VCC 14
D6 15
D7 16
D8 17
39 Q1
38 GND
37 Q2
36 Q3
35 GND
34 Q4
33 VCC
32 Q5
31 Q8
30 GND
29 Q7
18 19 20 21 22 23 24 25 26 27 28
GND WRCLK WREN1/PE9 WREN2 IR OR RDEN2 RDEN1 RDCLK VCC Q6
747807
Q1 VCC VCC Q2 Q3 GND GND Q4 VCC VCC Q5 Q6 GND GND Q7 NC
64 63 62 61 60 59 58 57 56 55 54 53 52 51 50 49
NC 1
Q0 2
GND 3
GND 4
ENO 5
NC 6
VCC 7
VCC 8
RESET 9
PEN 10
GND 11
GND 12
AF/AE 13
HF 14
VCC 15
VCC 16
48 NC
47 Q8
46 VCC
45 VCC
44 RDCLK
43 RDEN1
42 NC
41 RDEN2
40 OR
39 IR
38 WREN2
37 WREN1/PE9
36 WRCLK
35 GND
34 GND
33 NC
17 18 19 20 21 22 23 24 25 26 27 28 29 30 31 32
NC D0 D1 D2 GND GND D3 D4 NC D5 VCC VCC D6 D7 D8 NC
747808
VCC HF AF/AE GND PEN RESET VCC XO END GND Q0
6 5 4 3 2 1 44 43 42 41 40
D0 7
D1 8
D2 9
GND 10
D3 11
D4 12
D5 13
VCC 14
D6 15
D7 16
D6 17
39 Q1
38 GND
37 Q2
36 Q3
35 GND
34 Q4
33 VCC
32 Q5
31 Q8
30 GND
29 Q7
18 19 20 21 22 23 24 25 26 27 26
GND LDCK DP9 XI FULL EMPTY FL CASEN UNCK VCC Q6
747808
Q1 VCC VCC Q2 Q3 GND GND Q4 VCC VCC Q5 Q6 GND GND Q7 NC
64 63 62 61 60 59 58 57 56 55 54 53 52 51 50 49
NC 1
Q0 2
GND 3
GND 4
END 5
XD 6
VCC 7
VCC 8
RESET 9
PEN 10
GND 11
GND 12
AF/AE 13
HF 14
VCC 15
VCC 16
46 NC
47 Q8
46 VCC
45 VCC
44 UNCK
43 CASEN
42 NC
41 FL
40 EMPTY
39 FULL
38 XI
37 DP9
36 LDCK
35 GND
34 GND
33 NC
17 18 19 20 21 22 23 24 25 26 27 28 29 30 31 32
NC D0 D1 D2 GND GND D3 D4 NC D5 VCC VCC D8 D7 D8 NC
7478/1
1K 1
1Q 2
1Q 3
1J 4
2Q 5
2Q 6
GND 7
14 VCC
13 1S
12 CLR
11 2J
10 2S
9 CLK
8 2K
7478/1
1Q 1K NC VCC 1S
3 2 1 20 19
1Q 4
NC 5
1J 6
NC 7
2Q 8
18 CLR
17 NC
16 2J
15 NC
14 2S
9 10 11 12 13
2Q GND NC 2K CLK


747811
D15 9, D16 8, D17 7, GND 6, RDCLK 5, RDEN1 4, RDEN2 3, ENO 2, RESET 1, VCC 66, GND 67, OR 66, VCC 65, Q17 64, Q16 63, GND 62, Q15 61
D14 10, D13 11, D12 12, D11 13, D10 14, D9 15, VCC 16, D8 17, GND 16, D7 19, D8 20, D5 21, D4 22, D3 23, D2 24, D1 25, D0 26
50 VCC, 59 Q14, 58 Q13, 57 GND, 56 Q12, 55 Q11, 54 VCC, 53 Q10, 52 Q9, 51 GND, 50 Q6, 49 Q7, 48 VCC, 47 Q6, 46 Q5, 45 GND, 44 Q4
27 DAF, 28 GND, 29 WRCLK, 30 WREN1, 31 WREN2, 32 VCC, 33 AF/AE, 34 GND, 35 IR, 36 HF, 37 VCC, 38 Q0, 39 Q1, 40 GND, 41 Q2, 42 Q3, 43 VCC
747811
Q15 80, VCC 79, Q14 76, Q13 77, GND 76, GND 75, Q12 74, Q11 73, VCC 72, Q10 71, Q9 70, GND 69, Q8 68, Q7 67, VCC 66, Q8 65, Q5 64, GND 63, GND 62, Q4 61
NC 1, GND 2, GND 3, Q16 4, Q17 5, VCC 6, OR 7, GND 8, VCC 9, RESET 10, ENO 11, RDEN2 12, RDEN1 13, RDCLK 14, GND 15, D17 16, D16 17, D15 16, NC 19, NC 20
50 VCC, 59 VCC, 58 NC, 57 Q3, 56 Q2, 55 GND, 54 Q1, 53 Q0, 52 VCC, 51 HF, 50 IR, 49 GND, 46 GND, 47 AF/AE, 46 VCC, 45 WREN2, 44 WREN1, 43 WRCLK, 42 GND, 41 NC
21 NC, 22 D14, 23 D13, 24 D12, 25 D11, 28 D10, 27 D9, 28 VCC, 29 D8, 30 GND, 31 D7, 32 D6, 33 D5, 34 D4, 35 D3, 36 D2, 37 D1, 36 D0, 39 DAF, 40 NC
747813
RESET 1, D17 2, D16 3, D15 4, D14 5, D13 6, D12 7, D11 6, D10 9, VCC 10, D9 11, D8 12, GND 13, D7 14, D8 15, D5 16, D4 17, D3 16, D2 19, D1 20, D0 21, HF 22, PEN 23, AF/AE 24, WRCLK 25, WREN2 26, WREN1 27, IR 28
56 ENO1, 55 Q17, 54 Q16, 53 Q15, 52 GND, 51 Q14, 50 VCC, 49 Q13, 48 Q12, 47 Q11, 46 Q10, 45 Q9, 44 GND, 43 Q6, 42 Q7, 41 Q6, 40 Q5, 39 VCC, 38 Q4, 37 Q3, 36 Q2, 36 GND, 34 Q1, 33 Q0, 32 RDCLK, 31 RDEN, 30 ENO2, 29 DR
747814
RESET 1, D17 2, D16 3, D15 4, D14 5, D13 6, D12 7, D11 6, D10 9, VCC 10, D9 11, D6 12, GND 13, D7 14, D6 15, D5 16, D4 17, D3 16, D2 19, D1 20, D0 21, HF 22, PEN 23, AF/AE 24, LDCK 25, NC 26, NC 27, FULL 28
56 ENO1, 55 Q17, 54 Q16, 53 Q15, 52 GND, 51 Q14, 50 VCC, 49 Q13, 48 Q12, 47 Q11, 46 Q10, 45 Q9, 44 GND, 43 Q8, 42 Q7, 41 Q8, 40 Q5, 39 VCC, 38 Q4, 37 Q3, 36 Q2, 35 GND, 34 Q1, 33 Q0, 32 UNCK, 31 NC, 30 NC, 29 EMPTY

747815

1	A23	31	$\overline{AFA}$	61	$\overline{AFB}$	91	B23
2	A22	32	$\overline{FFA}$	62	$\overline{AEB}$	92	B24
3	A21	33	$\overline{CSA}$	63	$\overline{EFB}$	93	B25
4	GND	34	ENA	64	B0	94	B26
5	A20	35	CLKA	65	B1	95	VCC
6	A19	36	W/$\overline{RA}$	66	B2	96	B27
7	A18	37	VCC	67	GND	97	B28
8	A17	38	PGA	68	B3	98	B29
9	A16	39	$\overline{PEFA}$	69	B4	99	GND
10	A15	40	$\overline{MBF2}$	70	B5	100	B30
11	A14	41	MBA	71	B6	101	B31
12	A13	42	FS1	72	VCC	102	B32
13	A12	43	FS0	73	B7	103	B33
14	A11	44	ODD/$\overline{EVEN}$	74	B8	104	B34
15	A10	45	$\overline{RESET}$	75	B9	105	B35
16	GND	46	GND	76	GND	106	GND
17	A9	47	$\overline{BE}$	77	B10	107	A35
18	A8	48	SW1	78	B11	108	A34
19	A7	49	SW0	79	B12	109	A33
20	VCC	50	SIZ1	80	B13	110	A32
21	A6	51	SIZ0	81	B14	111	A31
22	A5	52	$\overline{MBF1}$	82	B15	112	A30
23	A4	53	$\overline{PEFB}$	83	B16	113	GND
24	A3	54	PGB	84	B17	114	A29
25	GND	55	VCC	85	B18	115	A28
26	A2	56	W/$\overline{RB}$	86	B19	116	A27
27	A1	57	CLKB	87	B20	117	VCC
28	A0	58	ENB	88	GND	118	A26
29	$\overline{EFA}$	59	$\overline{CSB}$	89	B21	119	A25
30	$\overline{AEA}$	60	$\overline{FFB}$	90	B22	120	A24

747816

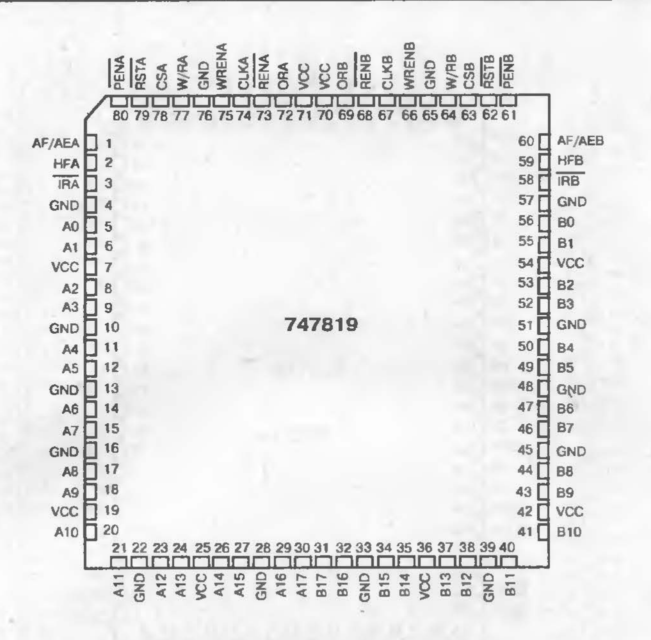
1	A23	31	$\overline{AFA}$	61	$\overline{AFB}$	91	B23
2	A22	32	$\overline{FFA}$	62	$\overline{AEB}$	92	B24
3	A21	33	$\overline{CSA}$	63	$\overline{EFB}$	93	B25
4	GND	34	ENA	64	B0	94	B26
5	A20	35	CLKA	65	B1	95	VCC
6	A19	36	W/$\overline{RA}$	66	B2	96	B27
7	A18	37	VCC	67	GND	97	B28
8	A17	38	PGA	68	B3	98	B29
9	A16	39	$\overline{PEFA}$	69	B4	99	GND
10	A15	40	$\overline{MBF2}$	70	B5	100	B30
11	A14	41	MBA	71	B6	101	B31
12	A13	42	FS1	72	VCC	102	B32
13	A12	43	FS0	73	B7	103	B33
14	A11	44	ODD/$\overline{EVEN}$	74	B8	104	B34
15	A10	45	$\overline{RESET}$	75	B9	105	B35
16	GND	46	GND	76	GND	106	GND
17	A9	47	$\overline{BE}$	77	B10	107	A35
18	A8	48	SW1	78	B11	108	A34
19	A7	49	$\overline{SW0}$	79	B12	109	A33
20	VCC	50	SIZ1	80	B13	110	A32
21	A6	51	SIZ0	81	B14	111	A31
22	A5	52	$\overline{MBF1}$	82	B15	112	A30
23	A4	53	$\overline{PEFB}$	83	B16	113	GND
24	A3	54	PGB	84	B17	114	A29
25	GND	55	VCC	85	B18	115	A28
26	A2	56	W/$\overline{RB}$	86	B19	116	A27
27	A1	57	CLKB	87	B20	117	VCC
28	A0	58	ENB	88	GND	118	A26
29	$\overline{EFA}$	59	$\overline{CSB}$	89	B21	119	A25
30	$\overline{AEA}$	60	$\overline{FFB}$	90	B22	120	A24

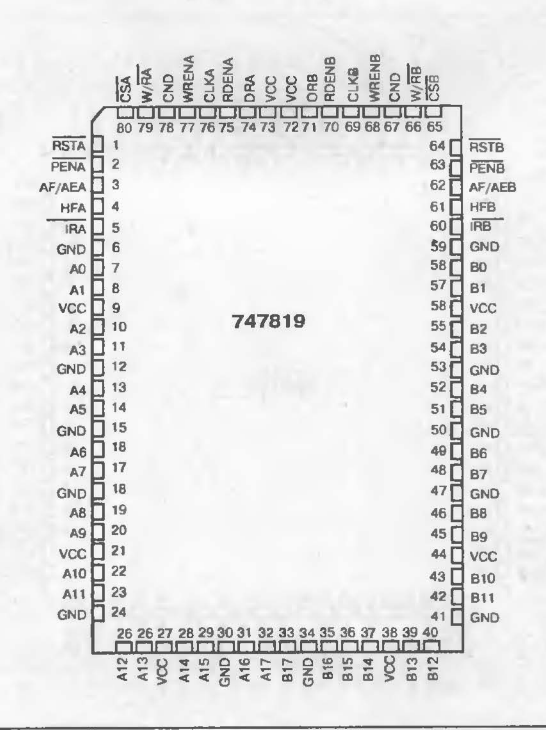
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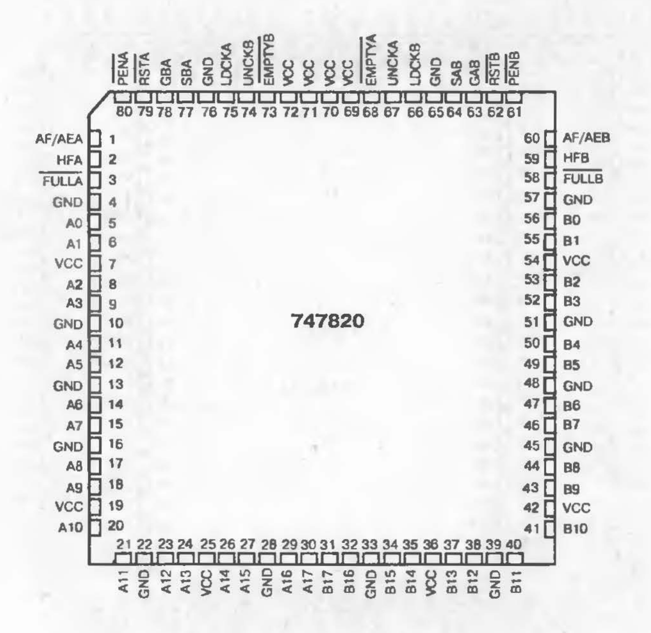
Pin	Signal	Pin	Signal	Pin	Signal	Pin	Signal
1	A23	31	$\overline{AFA}$	61	NC	91	B23
2	A22	32	$\overline{FFA}$	62	$\overline{AEB}$	92	B24
3	A21	33	$\overline{CSA}$	63	$\overline{EFB}$	93	B25
4	GND	34	ENA	64	B0	94	B26
5	A20	35	CLKA	65	B1	95	VCC
6	A19	36	W/$\overline{RA}$	66	B2	96	B27
7	A18	37	VCC	67	GND	97	B28
8	A17	38	PGA	68	B3	98	B29
9	A16	39	$\overline{PFFA}$	69	B4	99	GND
10	A15	40	$\overline{MBF2}$	70	B5	100	B30
11	A14	41	MBA	71	B6	101	B31
12	A13	42	FS1	72	VCC	102	B32
13	A12	43	FS0	73	B7	103	B33
14	A11	44	ODD/$\overline{EVEN}$	74	B8	104	B34
15	A10	45	$\overline{RESET}$	75	B9	105	B35
16	GND	46	GND	76	GND	106	GND
17	A9	47	$\overline{BE}$	77	B10	107	A35
18	A8	48	SW1	78	B11	108	A34
19	A7	49	$\overline{SW0}$	79	B12	109	A33
20	VCC	50	SIZ1	80	B13	110	A32
21	A8	51	SIZ0	81	B14	111	A31
22	A5	52	$\overline{MBF1}$	82	B15	112	A30
23	A4	53	$\overline{PEFB}$	83	B18	113	GND
24	A3	54	PGB	84	B17	114	A29
25	GND	55	VCC	85	B18	115	A28
26	A2	56	W/$\overline{RB}$	86	B19	116	A27
27	A1	57	CLKB	87	B20	117	VCC
28	A0	58	ENB	88	GND	118	A26
29	NC	59	$\overline{CSB}$	89	B21	119	A25
30	NC	60	$\overline{FFB}$	90	B22	120	A24

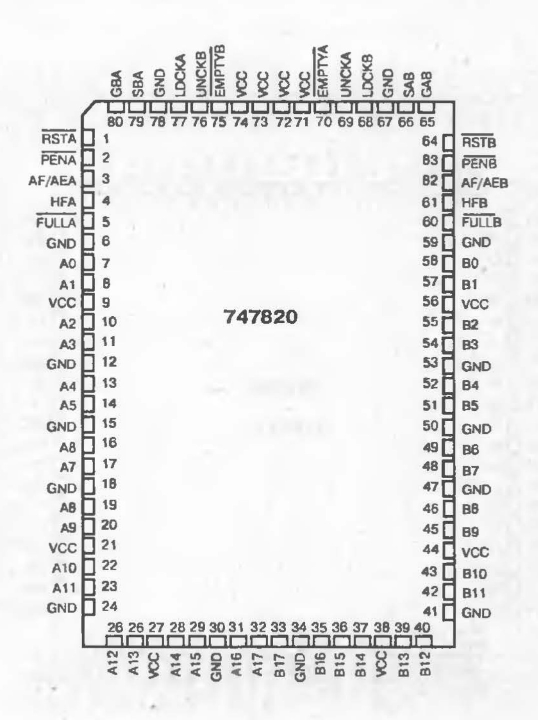
747818

Pin	Signal	Pin	Signal	Pin	Signal	Pin	Signal
1	A23	31	$\overline{AFA}$	61	NC	91	B23
2	A22	32	$\overline{FFA}$	62	$\overline{AEB}$	92	B24
3	A21	33	$\overline{CSA}$	63	$\overline{EFB}$	93	B25
4	GND	34	ENA	64	B0	94	B26
5	A20	35	CLKA	65	B1	95	VCC
6	A19	36	W/$\overline{RA}$	66	B2	96	B27
7	A18	37	VCC	67	GND	97	B28
8	A17	38	PGA	68	B3	98	B29
9	A16	39	$\overline{PFFA}$	69	B4	99	GND
10	A15	40	$\overline{MBF2}$	70	B5	100	B30
11	A14	41	MBA	71	B6	101	B31
12	A13	42	FS1	72	VCC	102	B32
13	A12	43	FS0	73	B7	103	B33
14	A11	44	ODD/$\overline{EVEN}$	74	B8	104	B34
15	A10	45	$\overline{RESET}$	75	B9	105	B35
16	GND	46	GND	76	GND	106	GND
17	A9	47	$\overline{BE}$	77	B10	107	A35
18	A8	48	SW1	78	B11	108	A34
19	A7	49	$\overline{SW0}$	79	B12	109	A33
20	VCC	50	SIZ1	80	B13	110	A32
21	A6	51	SIZ0	81	B14	111	A31
22	A5	52	$\overline{MBF1}$	82	B15	112	A30
23	A4	53	$\overline{PEFB}$	83	B16	113	GND
24	A3	54	PGB	84	B17	114	A29
25	GND	55	VCC	85	B18	115	A28
26	A2	56	W/$\overline{RB}$	86	B19	116	A27
27	A1	57	CLKB	87	B20	117	VCC
28	A0	58	ENB	88	GND	118	A26
29	NC	59	$\overline{CSB}$	89	B21	119	A25
30	NC	60	$\overline{FFB}$	90	B22	120	A24


747819
PENA RSTA CSA W/RA GND WRENA CLKA RENA ORA VCC VCC ORB RENB CLKB WRENB GND W/RB CSB RSTB PENB
80 79 78 77 76 75 74 73 72 71 70 69 68 67 66 65 64 63 62 61
AF/AEA 1
HFA 2
IRA 3
GND 4
A0 5
A1 6
VCC 7
A2 8
A3 9
GND 10
A4 11
A5 12
GND 13
A6 14
A7 15
GND 16
A8 17
A9 18
VCC 19
A10 20
60 AF/AEB
59 HFB
58 IRB
57 GND
56 B0
55 B1
54 VCC
53 B2
52 B3
51 GND
50 B4
49 B5
48 GND
47 B6
46 B7
45 GND
44 B8
43 B9
42 VCC
41 B10
21 22 23 24 25 26 27 28 29 30 31 32 33 34 35 36 37 38 39 40
A11 GND A12 A13 VCC A14 A15 GND A16 A17 B17 B16 GND B15 B14 VCC B13 B12 GND B11


747819
CSA W/RA CND WRENA CLKA RDENA DRA VCC VCC ORB RDENB CLKB WRENB CND W/RB CSB
80 79 78 77 76 75 74 73 72 71 70 69 68 67 66 65
RSTA 1
PENA 2
AF/AEA 3
HFA 4
IRA 5
GND 6
A0 7
A1 8
VCC 9
A2 10
A3 11
GND 12
A4 13
A5 14
GND 15
A6 18
A7 17
GND 18
A8 19
A9 20
VCC 21
A10 22
A11 23
GND 24
64 RSTB
63 PENB
62 AF/AEB
61 HFB
60 IRB
59 GND
58 B0
57 B1
58 VCC
55 B2
54 B3
53 GND
52 B4
51 B5
50 GND
49 B6
48 B7
47 GND
46 B8
45 B9
44 VCC
43 B10
42 B11
41 GND
26 26 27 28 29 30 31 32 33 34 35 36 37 38 39 40
A12 A13 VCC A14 A15 GND A16 A17 B17 GND B16 B15 B14 VCC B13 B12


747820
80 PENA
79 RSTA
78 GBA
77 SBA
76 GND
75 LDCKA
74 UNCKB
73 EMPTYB
72 VCC
71 VCC
70 VCC
69 VCC
68 EMPTYA
67 UNCKA
66 LDCKB
65 GND
64 SAB
63 GAB
62 RSTB
61 PENB
AF/AEA 1
HFA 2
FULLA 3
GND 4
A0 5
A1 6
VCC 7
A2 8
A3 9
GND 10
A4 11
A5 12
GND 13
A6 14
A7 15
GND 16
A8 17
A9 18
VCC 19
A10 20
21 A11
22 GND
23 A12
24 A13
25 VCC
26 A14
27 A15
28 GND
29 A16
30 A17
31 B17
32 B16
33 GND
34 B15
35 B14
36 VCC
37 B13
38 B12
39 GND
40 B11
60 AF/AEB
59 HFB
58 FULLB
57 GND
56 B0
55 B1
54 VCC
53 B2
52 B3
51 GND
50 B4
49 B5
48 GND
47 B6
46 B7
45 GND
44 B8
43 B9
42 VCC
41 B10


747820
80 GBA
79 SBA
78 GND
77 LDCKA
76 UNCKB
75 EMPTYB
74 VCC
73 VCC
72 VCC
71 VCC
70 EMPTYA
69 UNCKA
68 LDCKB
67 GND
66 SAB
65 GAB
RSTA 1
PENA 2
AF/AEA 3
HFA 4
FULLA 5
GND 6
A0 7
A1 8
VCC 9
A2 10
A3 11
GND 12
A4 13
A5 14
GND 15
A6 16
A7 17
GND 18
A8 19
A9 20
VCC 21
A10 22
A11 23
GND 24
26 A12
26 A13
27 VCC
28 A14
29 A15
30 GND
31 A16
32 A17
33 B17
34 GND
35 B16
36 B15
37 B14
38 VCC
39 B13
40 B12
64 RSTB
63 PENB
62 AF/AEB
61 HFB
60 FULLB
59 GND
58 B0
57 B1
56 VCC
55 B2
54 B3
53 GND
52 B4
51 B5
50 GND
49 B6
48 B7
47 GND
46 B8
45 B9
44 VCC
43 B10
42 B11
41 GND

747821

Pin	Signal	Pin	Signal	Pin	Signal	Pin	Signal
1	$\overline{CSA}$	31	GND	61	GND	91	VCC
2	W/$\overline{RA}$	32	A11	62	B12	92	IRB
3	ENA	33	A10	63	B13	93	ORB
4	CLKA	34	A9	64	B14	94	NC
5	VCC	35	A8	65	B15	95	$\overline{AFB}$
6	A31	36	A7	66	VCC	96	GND
7	A30	37	A6	67	B16	97	$\overline{AEB}$
8	GND	38	GND	68	B17	98	GND
9	A29	39	A5	69	GND	99	$\overline{MBF1}$
10	A28	40	A4	70	B18	100	MBB
11	A27	41	A3	71	B19	101	VCC
12	A26	42	VCC	72	B20	102	$\overline{RSTB}$
13	A25	43	A2	73	B21	103	FS1
14	A24	44	A1	74	B22	104	FS0
15	A23	45	A0	75	B23	105	$\overline{RDYB}$
16	GND	46	GND	76	GND	106	GND
17	A22	47	B0	77	B24	107	RFM
18	VCC	48	B1	78	B25	108	$\overline{MARK}$
19	A21	49	B2	79	VCC	109	$\overline{RDYA}$
20	A20	50	B3	80	B26	110	VCC
21	A19	51	B4	81	B27	111	$\overline{RSTA}$
22	A18	52	B5	82	B28	112	MBA
23	GND	53	GND	83	B29	113	VCC
24	A17	54	B6	84	B30	114	$\overline{MBF2}$
25	A16	55	VCC	85	B31	115	$\overline{AFE}$
26	A15	56	B7	86	GND	116	$\overline{AFA}$
27	A14	57	B8	87	CLKB	117	NC
28	A13	58	B9	88	ENB	118	ORA
29	VCC	59	B10	89	$\overline{W}$/RB	119	IRA
30	A12	60	B11	90	$\overline{CSB}$	120	GND

747822

Pin	Signal	Pin	Signal	Pin	Signal	Pin	Signal
1	A35	31	GND	61	GND	91	VCC
2	A34	32	A11	62	B12	92	CLKB
3	A33	33	A10	63	B13	93	ENB
4	A32	34	A9	64	B14	94	$\overline{W}$/RB
5	VCC	35	A8	65	B15	95	$\overline{CSB}$
6	A31	36	A7	66	VCC	96	GND
7	A30	37	A6	67	B16	97	IRB
8	GND	38	GND	68	B17	98	ORB
9	A29	39	A5	69	GND	99	$\overline{AFB}$
10	A28	40	A4	70	B18	100	$\overline{AEB}$
11	A27	41	A3	71	B19	101	VCC
12	A26	42	VCC	72	B20	102	$\overline{MBF1}$
13	A25	43	A2	73	B21	103	MBB
14	A24	44	A1	74	B22	104	$\overline{RST2}$
15	A23	45	A0	75	B23	105	FS1
16	GND	46	GND	76	GND	106	GND
17	A22	47	B0	77	B24	107	FS0
18	VCC	48	B1	78	B25	108	$\overline{RST1}$
19	A21	49	B2	79	VCC	109	MBA
20	A20	50	B3	80	B26	110	$\overline{MBF2}$
21	A19	51	B4	81	B27	111	$\overline{AEA}$
22	A18	52	B5	82	B28	112	$\overline{AFA}$
23	GND	53	GND	83	B29	113	VCC
24	A17	54	B6	84	B30	114	ORA
25	A16	55	VCC	85	B31	115	IRA
26	A15	56	B7	86	GND	116	$\overline{CSA}$
27	A14	57	B8	87	B32	117	W/$\overline{RA}$
28	A13	58	B9	88	B33	118	ENA
29	VCC	59	B10	89	B34	119	CLKA
30	A12	60	B11	90	B35	120	GND

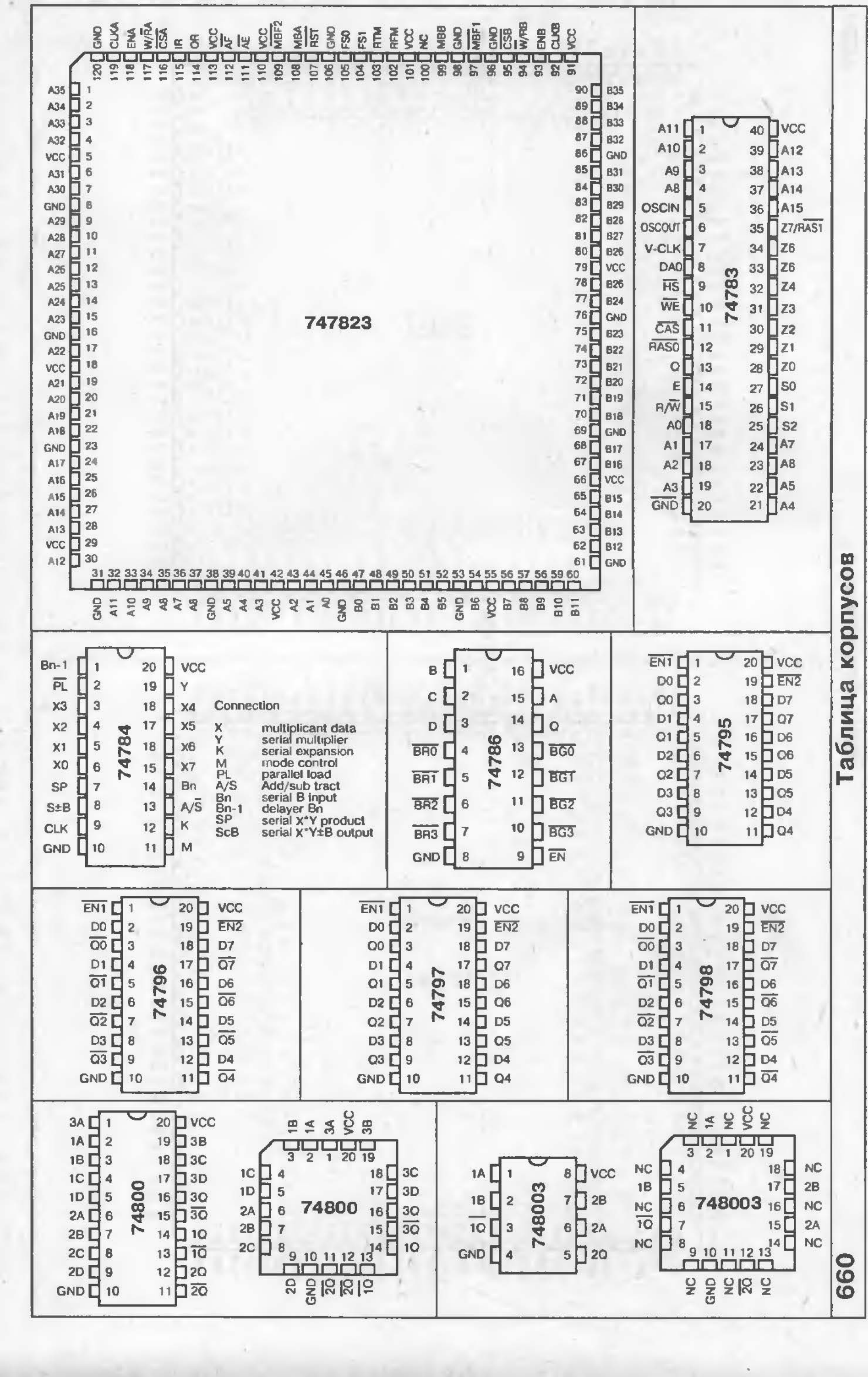
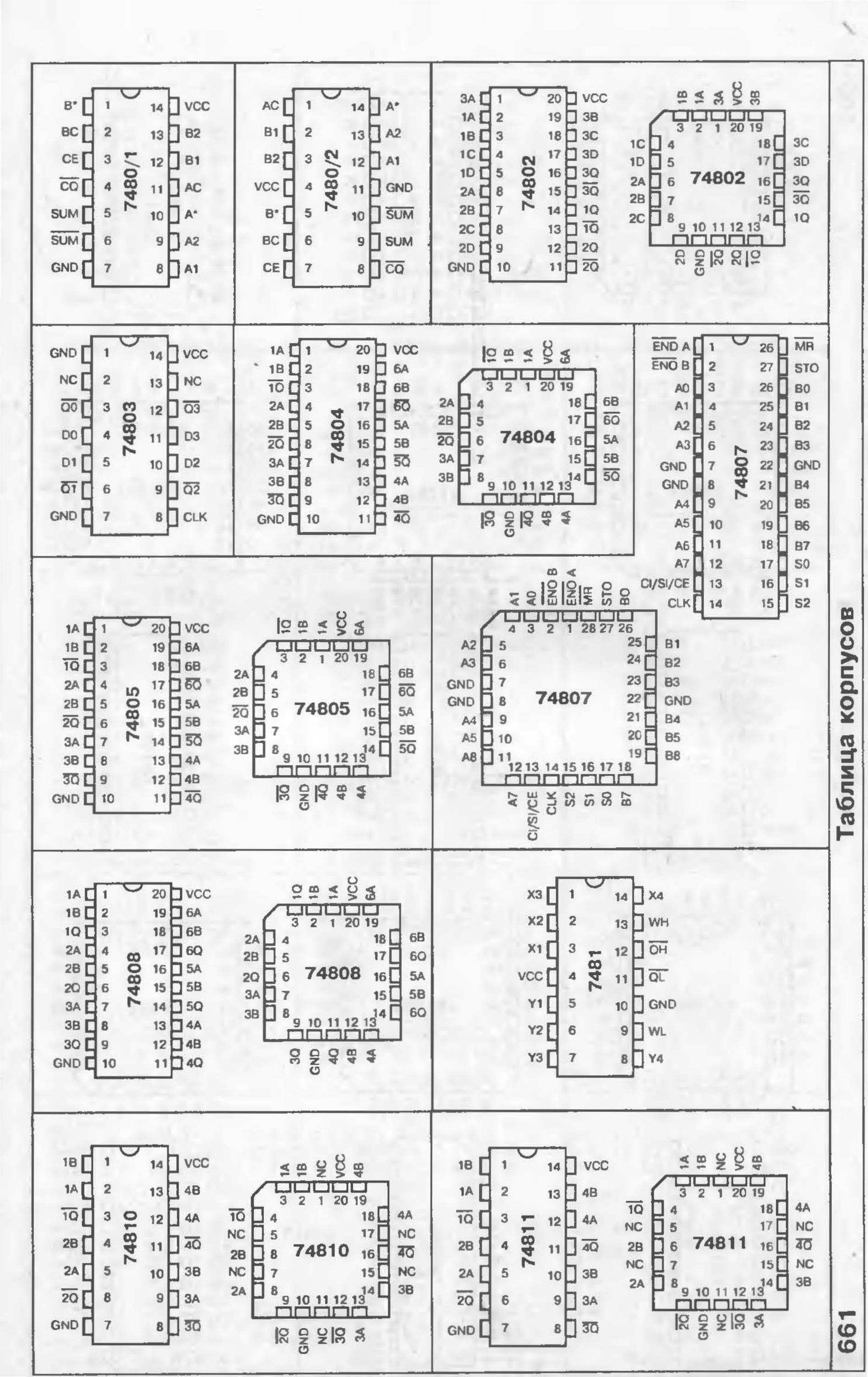
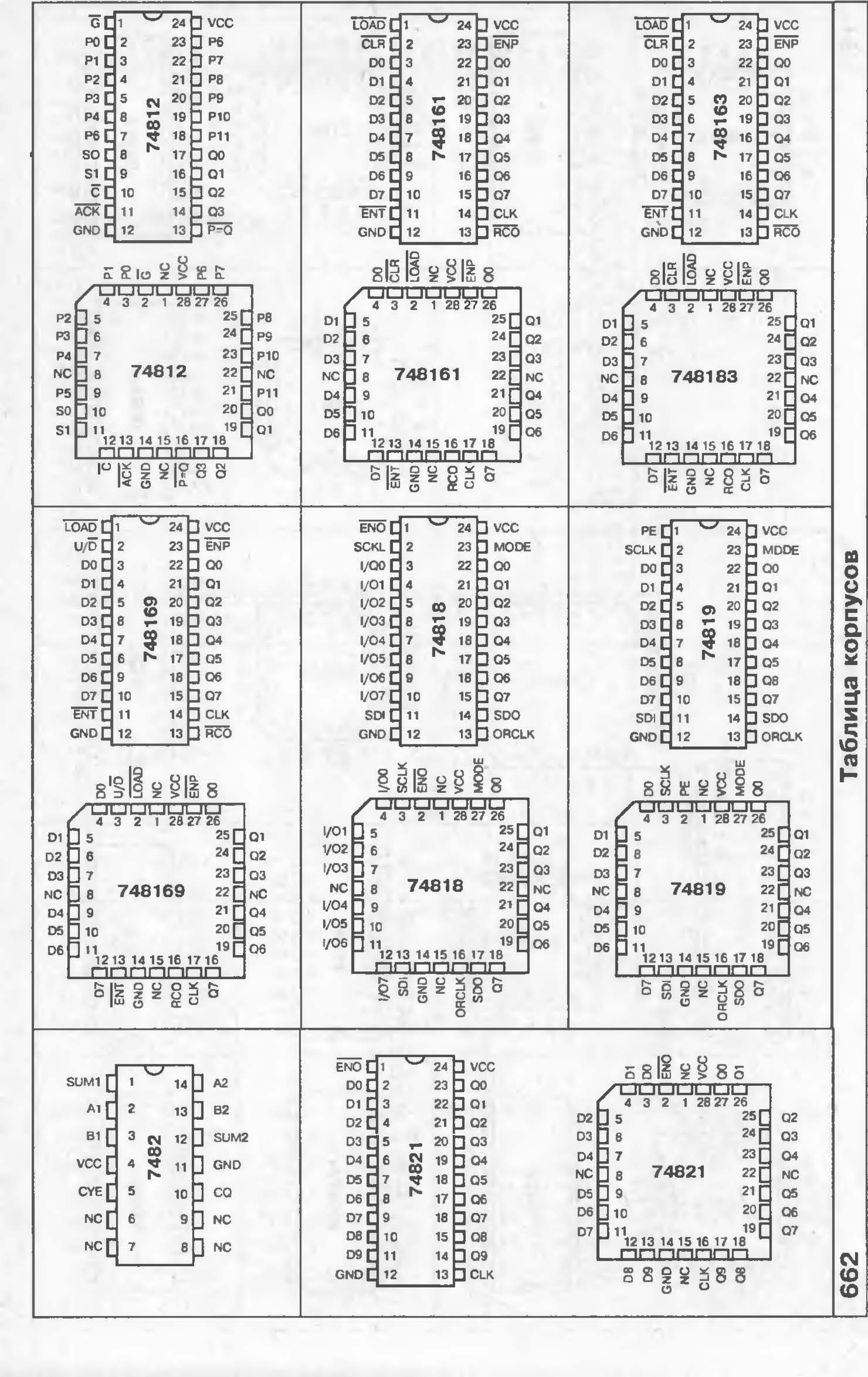
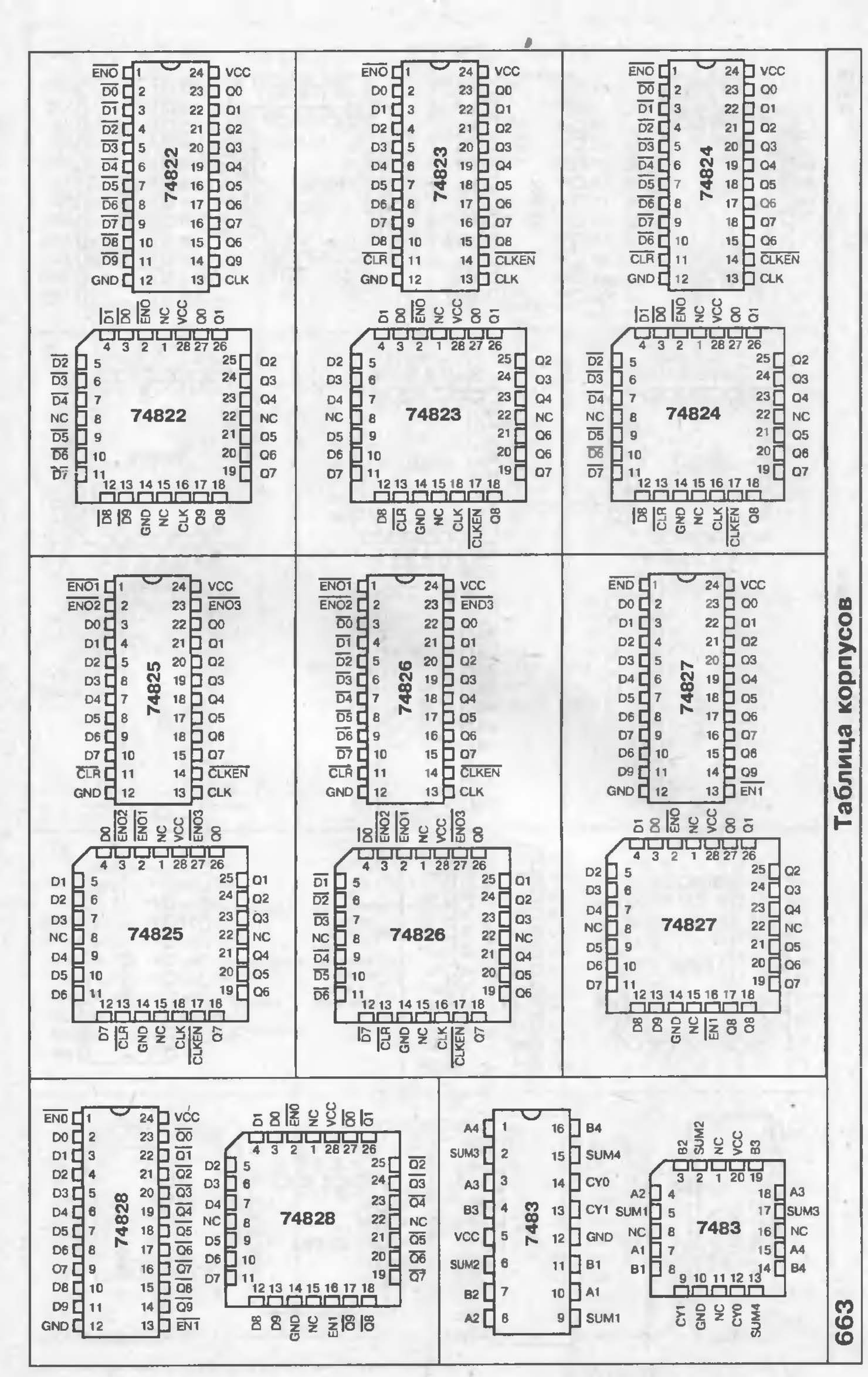


Таблица корпусов


7480/1
7480/2
74802
74803
74804
74807
74805
74808
7481
74810
74811


74812
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748183
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7482
74821
74821


74822
ENO 1 24 VCC
D0 2 23 Q0
D1 3 22 Q1
D2 4 21 Q2
D3 5 20 Q3
D4 6 19 Q4
D5 7 18 Q5
D6 8 17 Q6
D7 9 16 Q7
D8 10 15 Q8
D9 11 14 Q9
GND 12 13 CLK
74822
D1 D0 ENO NC VCC Q0 Q1
4 3 2 1 28 27 26
D2 5 25 Q2
D3 6 24 Q3
D4 7 23 Q4
NC 8 22 NC
D5 9 21 Q5
D6 10 20 Q6
D7 11 19 Q7
12 13 14 15 16 17 18
D8 D9 GND NC CLK Q9 Q8
74823
ENO 1 24 VCC
D0 2 23 Q0
D1 3 22 Q1
D2 4 21 Q2
D3 5 20 Q3
D4 6 19 Q4
D5 7 18 Q5
D6 8 17 Q6
D7 9 16 Q7
D8 10 15 Q8
CLR 11 14 CLKEN
GND 12 13 CLK
74823
D1 D0 ENO NC VCC Q0 Q1
4 3 2 1 28 27 26
D2 5 25 Q2
D3 6 24 Q3
D4 7 23 Q4
NC 8 22 NC
D5 9 21 Q6
D6 10 20 Q6
D7 11 19 Q7
12 13 14 15 16 17 18
D8 CLR GND NC CLK CLKEN Q8
74824
ENO 1 24 VCC
D0 2 23 Q0
D1 3 22 Q1
D2 4 21 Q2
D3 5 20 Q3
D4 6 19 Q4
D5 7 18 Q5
D6 8 17 Q6
D7 9 16 Q7
D6 10 15 Q6
CLR 11 14 CLKEN
GND 12 13 CLK
74824
D1 D0 ENO NC VCC Q0 Q1
4 3 2 1 28 27 26
D2 5 25 Q2
D3 6 24 Q3
D4 7 23 Q4
NC 8 22 NC
D5 9 21 Q5
D6 10 20 Q6
D7 11 19 Q7
12 13 14 15 16 17 18
D8 CLR GND NC CLK CLKEN Q8
74825
ENO1 1 24 VCC
ENO2 2 23 ENO3
D0 3 22 Q0
D1 4 21 Q1
D2 5 20 Q2
D3 6 19 Q3
D4 7 18 Q4
D5 8 17 Q5
D6 9 16 Q6
D7 10 15 Q7
CLR 11 14 CLKEN
GND 12 13 CLK
74825
D0 ENO2 ENO1 NC VCC ENO3 Q0
4 3 2 1 28 27 26
D1 5 25 Q1
D2 6 24 Q2
D3 7 23 Q3
NC 8 22 NC
D4 9 21 Q4
D5 10 20 Q5
D6 11 19 Q6
12 13 14 15 16 17 18
D7 CLR GND NC CLK CLKEN Q7
74826
ENO1 1 24 VCC
ENO2 2 23 END3
D0 3 22 Q0
D1 4 21 Q1
D2 5 20 Q2
D3 6 19 Q3
D4 7 18 Q4
D5 8 17 Q5
D6 9 16 Q6
D7 10 15 Q7
CLR 11 14 CLKEN
GND 12 13 CLK
74826
D0 ENO2 ENO1 NC VCC ENO3 Q0
4 3 2 1 28 27 26
D1 5 25 Q1
D2 6 24 Q2
D3 7 23 Q3
NC 8 22 NC
D4 9 21 Q4
D5 10 20 Q5
D6 11 19 Q6
12 13 14 15 16 17 18
D7 CLR GND NC CLK CLKEN Q7
74827
END 1 24 VCC
D0 2 23 Q0
D1 3 22 Q1
D2 4 21 Q2
D3 5 20 Q3
D4 6 19 Q4
D5 7 18 Q5
D6 8 17 Q6
D7 9 16 Q7
D6 10 15 Q8
D9 11 14 Q9
GND 12 13 EN1
74827
D1 D0 ENO NC VCC Q0 Q1
4 3 2 1 28 27 26
D2 5 25 Q2
D3 6 24 Q3
D4 7 23 Q4
NC 8 22 NC
D5 9 21 Q5
D6 10 20 Q6
D7 11 19 Q7
12 13 14 15 16 17 18
D8 D9 GND NC EN1 Q8 Q8
74828
ENO 1 24 VCC
D0 2 23 Q0
D1 3 22 Q1
D2 4 21 Q2
D3 5 20 Q3
D4 6 19 Q4
D5 7 18 Q5
D6 8 17 Q6
O7 9 16 Q7
D8 10 15 Q8
D9 11 14 Q9
GND 12 13 EN1
74828
D1 D0 ENO NC VCC Q0 Q1
4 3 2 1 28 27 26
D2 5 25 Q2
D3 6 24 Q3
D4 7 23 Q4
NC 8 22 NC
D5 9 21 Q5
D6 10 20 Q6
D7 11 19 Q7
12 13 14 15 16 17 18
D8 D9 GND NC EN1 Q9 Q8
7483
A4 1 16 B4
SUM3 2 15 SUM4
A3 3 14 CY0
B3 4 13 CY1
VCC 5 12 GND
SUM2 6 11 B1
B2 7 10 A1
A2 8 9 SUM1
7483
B2 SUM2 NC VCC B3
3 2 1 20 19
A2 4 18 A3
SUM1 5 17 SUM3
NC 6 16 NC
A1 7 15 A4
B1 8 14 B4
9 10 11 12 13
CY1 GND NC CY0 SUM4

741832

Pin	Name	Pin	Name
1	1A	20	VCC
2	1B	19	6A
3	1O	18	6B
4	2A	17	6Q
5	2B	16	5A
6	2O	15	5B
7	3A	14	5Q
8	3B	13	4A
9	3Q	12	4B
10	GND	11	4O

74832

Pin	Name	Pin	Name
3	1Q	18	6B
2	1B	17	6Q
1	1A	16	5A
20	VCC	15	5B
19	6A	14	5Q
4	2A	9	3Q
5	2B	10	GND
6	2Q	11	4Q
7	3A	12	4B
8	3B	13	4A

74835

Pin	Name	Pin	Name
1	$\overline{ENP}$	24	VCC
2	CLK	23	D3B
3	D4A	22	D3A
4	D4B	21	D2B
5	D5A	20	D2A
6	D5B	19	D1B
7	D6A	18	D1A
6	D6B	17	D0B
9	D7A	16	D0A
10	D7B	15	DS
11	Q7	14	SEL A/$\overline{B}$
12	GND	13	ENL

7484

Pin	Name	Pin	Name
1	X4	16	WH1
2	X3	15	WH2
3	X2	14	QH
4	X1	13	QL
5	VCC	12	GND
6	Y1	11	WL1
7	Y2	10	WL2
8	Y3	9	Y4

741838

Pin	Name	Pin	Name
1	JS4	20	VCC
2	JS3	19	CASCI
3	JS2	18	CASCO
4	JS1	17	PS4
5	JS0	16	PS3
6	CLK	15	PS2
7	SUB0	14	PS1
8	SUB1	13	PS0
9	JMP	12	$\overline{RESET}$
10	GND	11	$\overline{INT}$

Connections:

JS0-JS4	jump state inputs
JMP	jump input
SUB0-SUB1	subroutine inputs
INT	interrupt input
RESET	reset input
PS0-PS4	present state outputs

74841

Pin	Name	Pin	Name
1	$\overline{ENO}$	24	VCC
2	D0	23	Q0
3	D1	22	Q1
4	D2	21	Q2
5	D3	20	Q3
6	D4	19	Q4
7	D5	18	Q5
8	D6	17	Q6
9	D7	16	Q7
10	D8	15	Q6
11	D9	14	Q9
12	GND	13	ENL

74841 (PLCC)

Pin	Name	Pin	Name
4	D1	25	Q2
3	D0	24	Q3
2	$\overline{ENO}$	23	Q4
1	NC	22	NC
28	VCC	21	Q5
27	Q0	20	Q6
26	Q1	19	Q7
5	D2	12	D8
6	D3	13	D9
7	D4	14	GND
8	NC	15	NC
9	D5	16	ENL
10	D6	17	Q9
11	D7	18	Q8

74842

Pin	Name	Pin	Name
1	$\overline{EN0}$	24	VCC
2	$\overline{D0}$	23	Q0
3	$\overline{D1}$	22	Q1
4	$\overline{D2}$	21	Q2
5	$\overline{D3}$	20	Q3
6	$\overline{D4}$	19	Q4
7	$\overline{D5}$	18	Q5
8	$\overline{D6}$	17	Q6
9	$\overline{D7}$	16	Q7
10	$\overline{D8}$	15	Q8
11	$\overline{D9}$	14	Q9
12	GND	13	ENL

74842 (PLCC)

Pin	Name	Pin	Name
4	$\overline{D1}$	25	Q2
3	$\overline{D0}$	24	Q3
2	$\overline{EN0}$	23	Q4
1	NC	22	NC
28	VCC	21	Q5
27	Q0	20	Q6
26	Q1	19	Q7
5	$\overline{D2}$	12	$\overline{D8}$
6	$\overline{D3}$	13	$\overline{D9}$
7	$\overline{D4}$	14	GND
8	NC	15	NC
9	$\overline{D5}$	16	ENL
10	$\overline{D6}$	17	Q9
11	$\overline{D7}$	18	Q8

74843

Pin	Name	Pin	Name
1	$\overline{EN0}$	24	VCC
2	D0	23	Q0
3	D1	22	Q1
4	D2	21	Q2
5	D3	20	Q3
6	D4	19	Q4
7	D5	18	Q5
8	D6	17	Q6
9	D7	16	Q7
10	D8	15	Q6
11	$\overline{CLR}$	14	$\overline{S}$
12	GND	13	ENL

74843 (PLCC)

Pin	Name	Pin	Name
4	D1	25	Q2
3	D0	24	Q3
2	$\overline{EN0}$	23	Q4
1	NC	22	NC
28	VCC	21	Q5
27	Q0	20	Q6
26	Q1	19	Q7
5	D2	12	D8
6	D3	13	$\overline{CLR}$
7	D4	14	GND
8	NC	15	NC
9	D5	16	ENL
10	D6	17	S
11	D7	18	Q8

74844

Pin	Name	Pin	Name
1	EN0	24	VCC
2	$\overline{D0}$	23	Q0
3	$\overline{D1}$	22	Q1
4	$\overline{D2}$	21	Q2
5	$\overline{D3}$	20	Q3
6	$\overline{D4}$	19	Q4
7	$\overline{D5}$	18	Q5
8	$\overline{D8}$	17	Q6
9	$\overline{D7}$	16	Q7
10	$\overline{D8}$	15	Q8
11	$\overline{CLR}$	14	$\overline{S}$
12	GND	13	ENL

74844 (PLCC)

Pin	Name	Pin	Name
4	$\overline{D1}$	25	Q2
3	$\overline{D0}$	24	Q3
2	$\overline{EN0}$	23	Q4
1	NC	22	NC
28	VCC	21	Q5
27	Q0	20	Q6
26	Q1	19	Q7
5	$\overline{D2}$	12	$\overline{D8}$
6	$\overline{D3}$	13	$\overline{CLR}$
7	D4	14	GND
8	$\overline{NC}$	15	NC
9	$\overline{D5}$	16	ENL
10	$\overline{D6}$	17	S
11	D7	18	Q8

74845

Pin	Name	Pin	Name
1	$\overline{ENO1}$	24	VCC
2	$\overline{ENO2}$	23	$\overline{END3}$
3	D0	22	Q0
4	D1	21	Q1
5	D2	20	Q2
6	D3	19	Q3
7	D4	18	Q4
8	D5	17	Q5
9	D6	18	Q6
10	D7	15	Q7
11	CLR	14	$\overline{S}$
12	GND	13	ENL

74854 (PLCC)

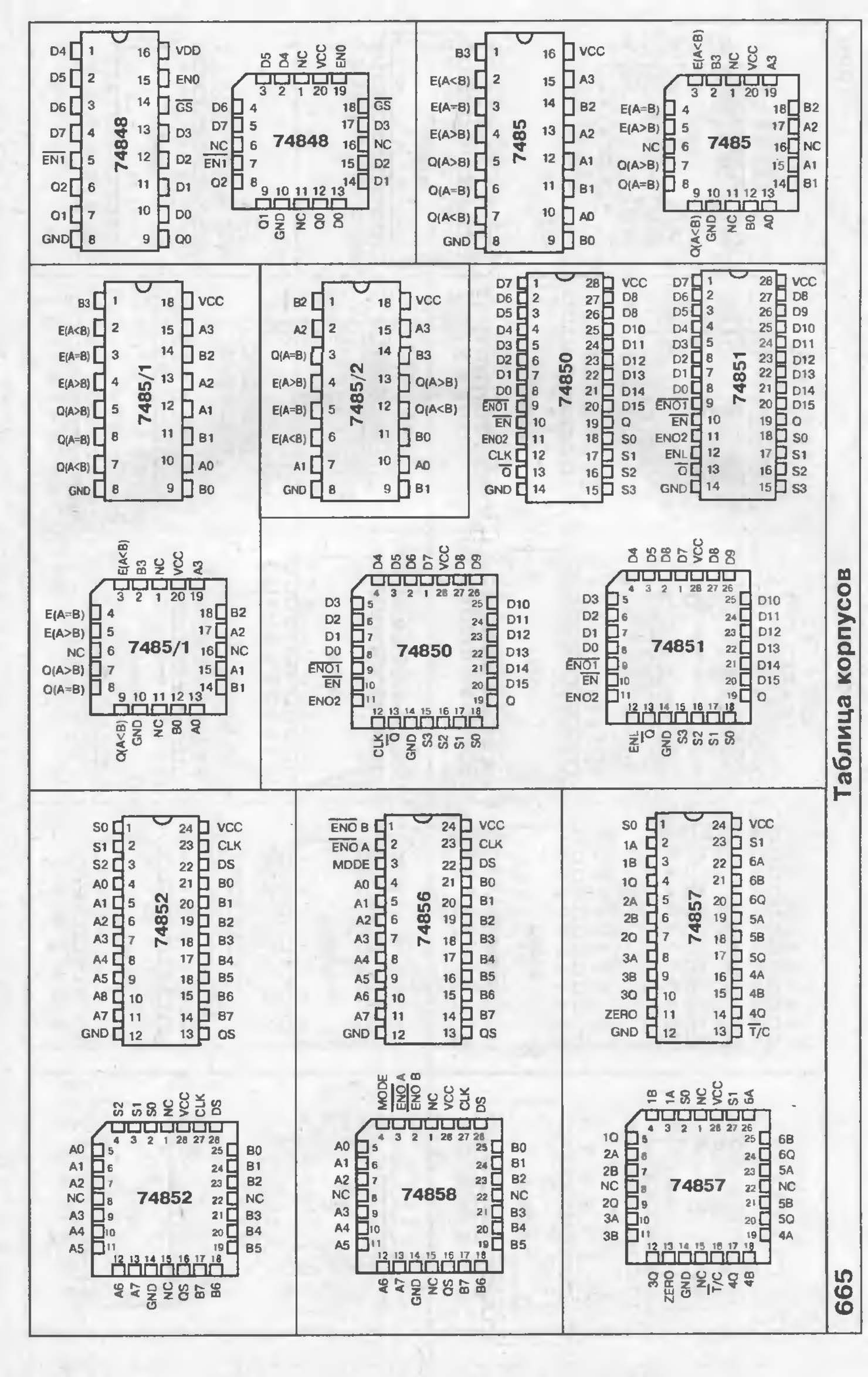
Pin	Name	Pin	Name
4	D0	25	Q1
3	$\overline{ENO2}$	24	Q2
2	$\overline{ENO1}$	23	Q3
1	NC	22	NC
28	VCC	21	Q4
27	$\overline{ENO3}$	20	Q5
28	Q0	19	Q6
5	D1	12	D7
6	D2	13	$\overline{CLR}$
7	D3	14	GND
8	NC	15	NC
9	D4	16	ENL
10	D5	17	S
11	D6	18	Q7

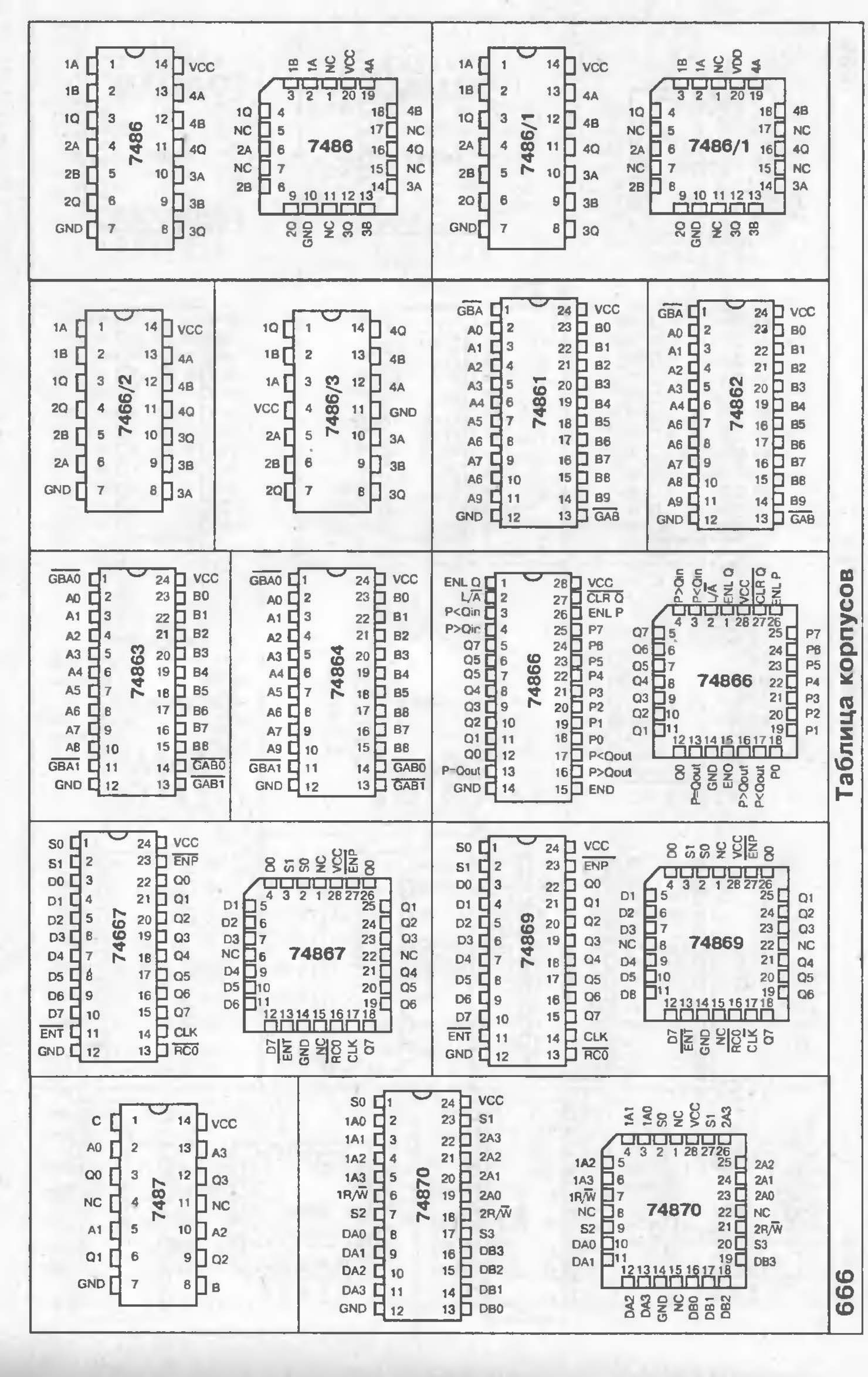
74846

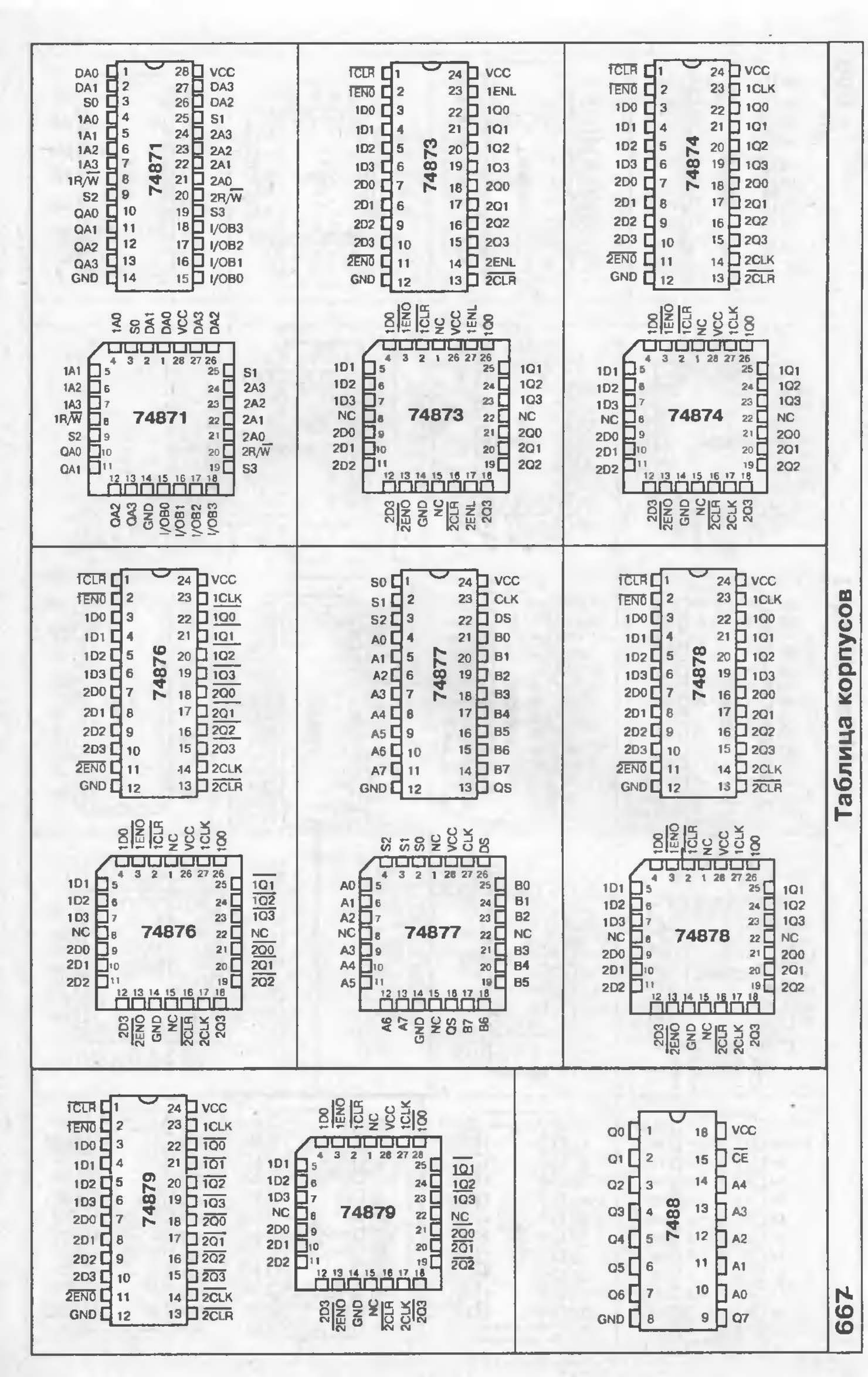
Pin	Name	Pin	Name
1	$\overline{ENO1}$	24	VCC
2	$\overline{END2}$	23	$\overline{ENO3}$
3	D0	22	Q0
4	D1	21	Q1
5	D2	20	Q2
6	D3	19	Q3
7	D4	18	Q4
8	D5	17	Q5
9	D6	16	Q6
10	D7	15	Q7
11	CLR	14	$\overline{S}$
12	GND	13	ENL

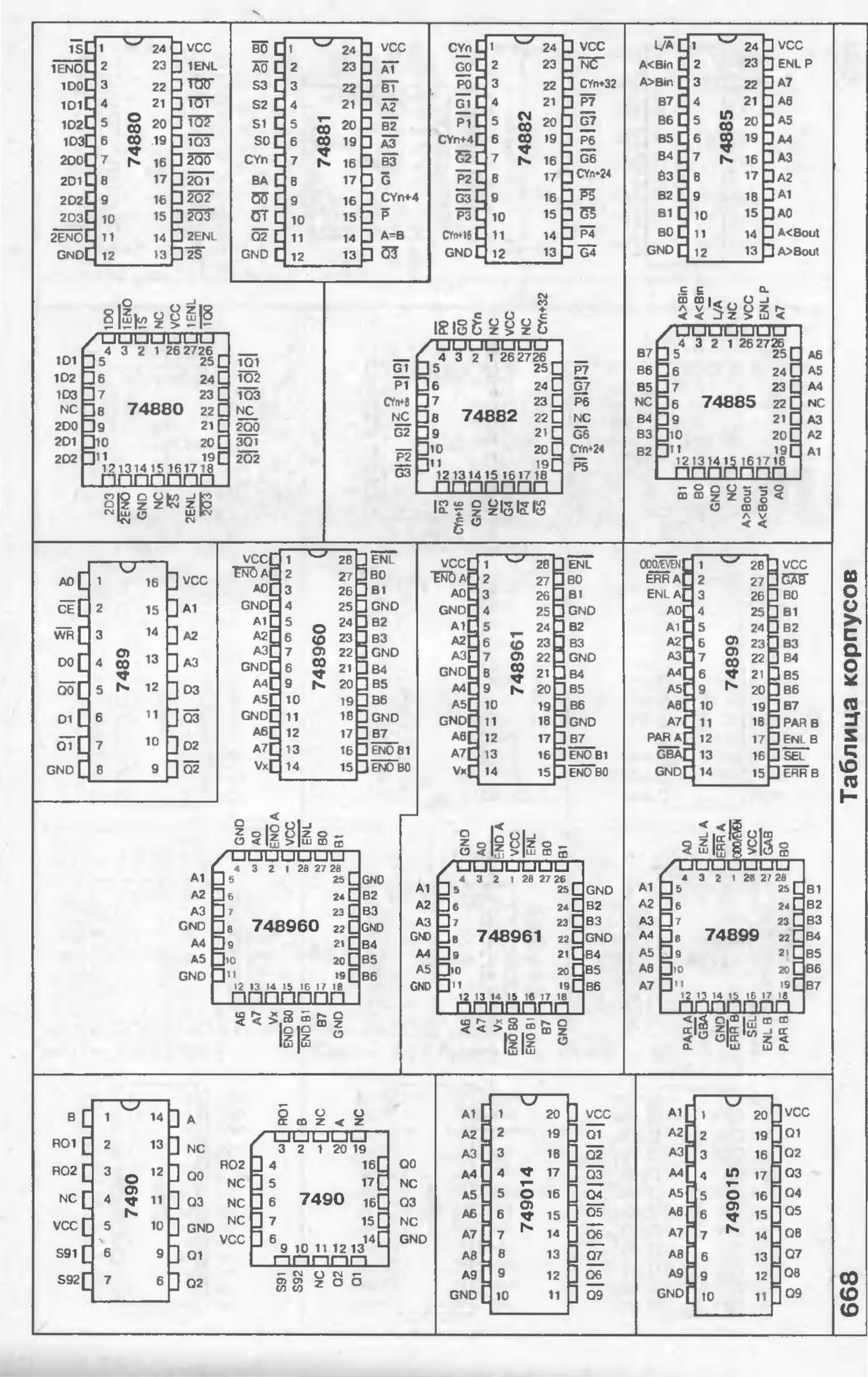
74846 (PLCC)

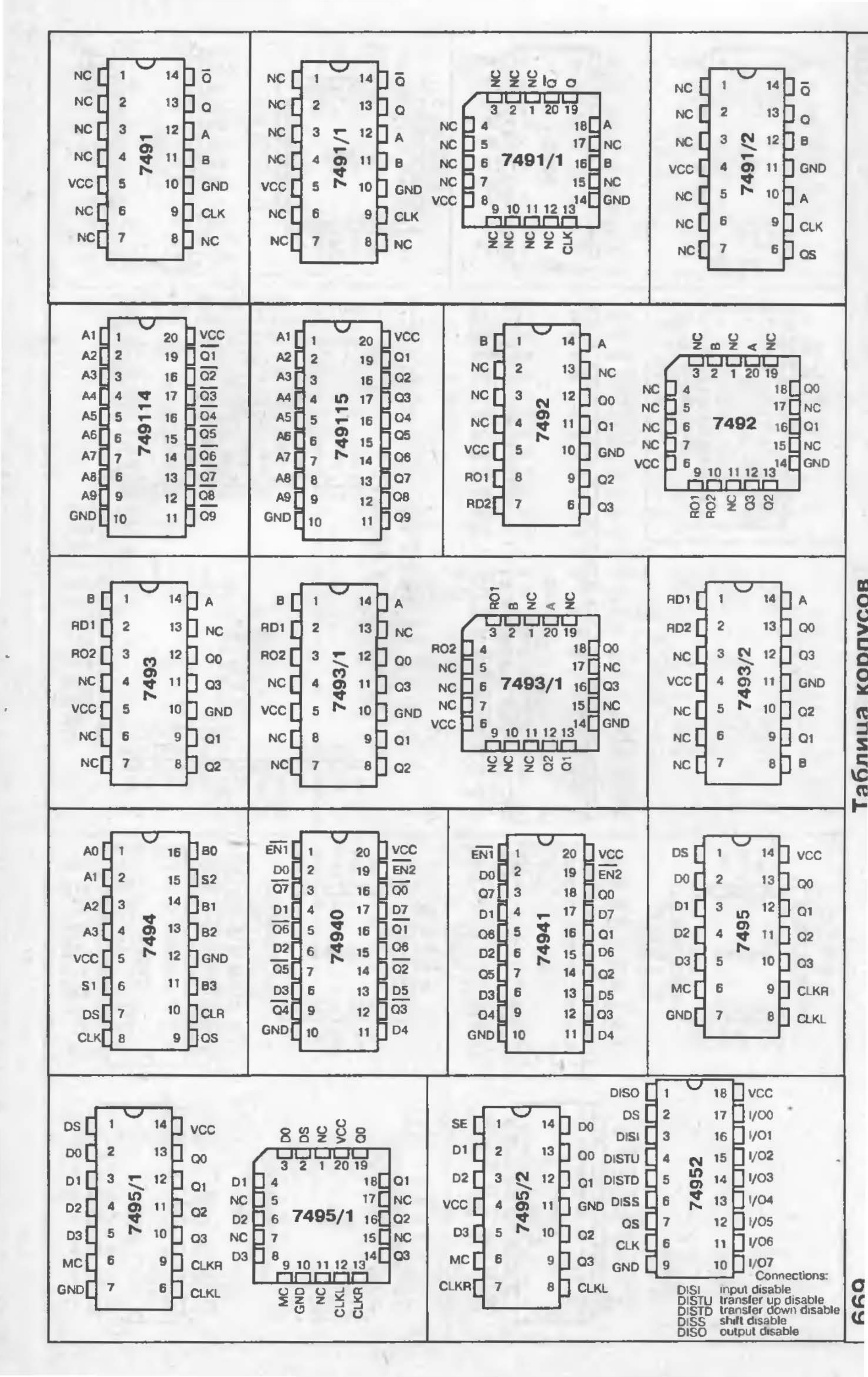
Pin	Name	Pin	Name
4	$\overline{D0}$	25	Q1
3	$\overline{ENO2}$	24	Q2
2	$\overline{ENO1}$	23	Q3
1	NC	22	NC
28	VCC	21	Q4
27	$\overline{ENO3}$	20	Q5
26	Q0	19	Q6
5	$\overline{D1}$	12	$\overline{D7}$
6	$\overline{D2}$	13	$\overline{CLR}$
7	D3	14	GND
8	$\overline{NC}$	15	NC
9	$\overline{D4}$	16	ENL
10	$\overline{D5}$	17	S
11	D8	18	Q7

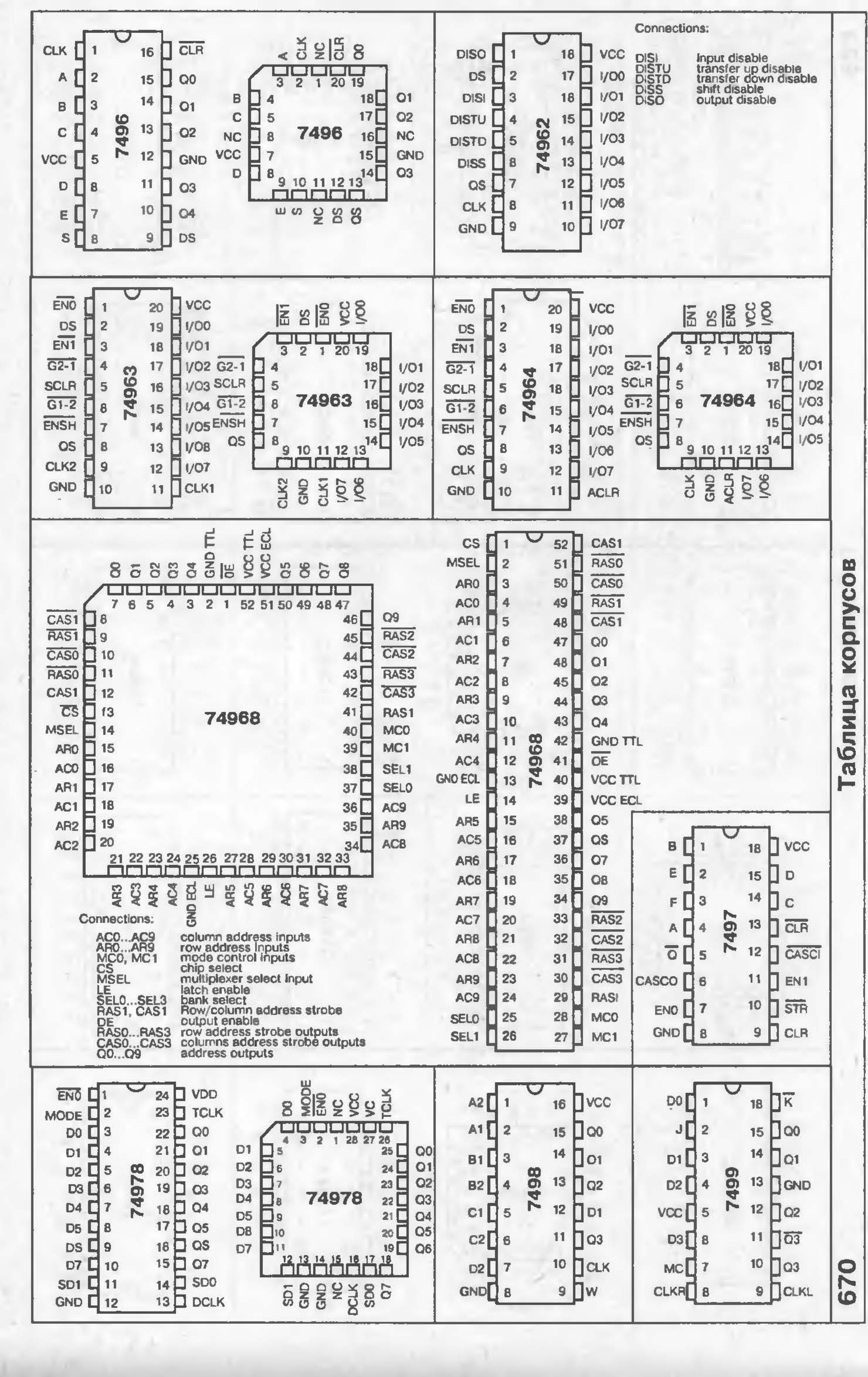

74848
D4 D5 D6 D7 EN1 Q2 Q1 GND Q0 D0 D1 D2 D3 GS EN0 VDD
74848
D5 D4 NC VCC EN0 GS D3 NC D2 D1 D0 Q0 NC GND Q1 Q2 EN1 NC D7 D6
7485
B3 E(A<B) E(A=B) E(A>B) Q(A>B) Q(A=B) Q(A<B) GND B0 A0 B1 A1 A2 B2 A3 VCC
7485
E(A<B) B3 NC VCC A3 B2 A2 NC A1 B1 A0 B0 NC GND Q(A<B) Q(A=B) Q(A>B) NC E(A>B) E(A=B)
7485/1
B3 E(A<B) E(A=B) E(A>B) Q(A>B) Q(A=B) Q(A<B) GND B0 A0 B1 A1 A2 B2 A3 VCC
7485/2
B2 A2 Q(A=B) E(A>B) E(A=B) E(A<B) A1 GND B1 A0 B0 Q(A<B) Q(A>B) B3 A3 VCC
74850
D7 D6 D5 D4 D3 D2 D1 D0 ENO1 EN ENO2 CLK Q GND S3 S2 S1 S0 Q D15 D14 D13 D12 D11 D10 D8 D8 VCC
74851
D7 D6 D5 D4 D3 D2 D1 D0 ENO1 EN ENO2 ENL Q GND S3 S2 S1 S0 Q D15 D14 D13 D12 D11 D10 D9 D8 VCC
7485/1
E(A<B) B3 NC VCC A3 B2 A2 NC A1 B1 A0 B0 NC GND Q(A<B) Q(A=B) Q(A>B) NC E(A>B) E(A=B)
74850
D4 D5 D6 D7 VCC D8 D9 D10 D11 D12 D13 D14 D15 Q S0 S1 S2 S3 GND Q CLK ENO2 EN ENO1 D0 D1 D2 D3
74851
D4 D5 D8 D7 VCC D8 D9 D10 D11 D12 D13 D14 D15 Q S0 S1 S2 S3 GND Q ENL ENO2 EN ENO1 D0 D1 D2 D3
74852
S0 S1 S2 A0 A1 A2 A3 A4 A5 A8 A7 GND QS B7 B6 B5 B4 B3 B2 B1 B0 DS CLK VCC
74856
ENO B ENO A MDDE A0 A1 A2 A3 A4 A5 A6 A7 GND QS B7 B6 B5 B4 B3 B2 B1 B0 DS CLK VCC
74857
S0 1A 1B 1Q 2A 2B 2Q 3A 3B 3Q ZERO GND T/C 4Q 4B 4A 5Q 5B 5A 6Q 6B 6A S1 VCC
74852
S2 S1 S0 NC VCC CLK DS B0 B1 B2 NC B3 B4 B5 B6 B7 QS NC GND A7 A6 A5 A4 A3 NC A2 A1 A0
74858
MODE ENO A ENO B NC VCC CLK DS B0 B1 B2 NC B3 B4 B5 B6 B7 QS NC GND A7 A6 A5 A4 A3 NC A2 A1 A0
74857
1B 1A S0 NC VCC S1 6A 6B 6Q 5A NC 5B 5Q 4A 4B 4Q T/C NC GND ZERO 3Q 3B 3A 2Q NC 2B 2A 1Q

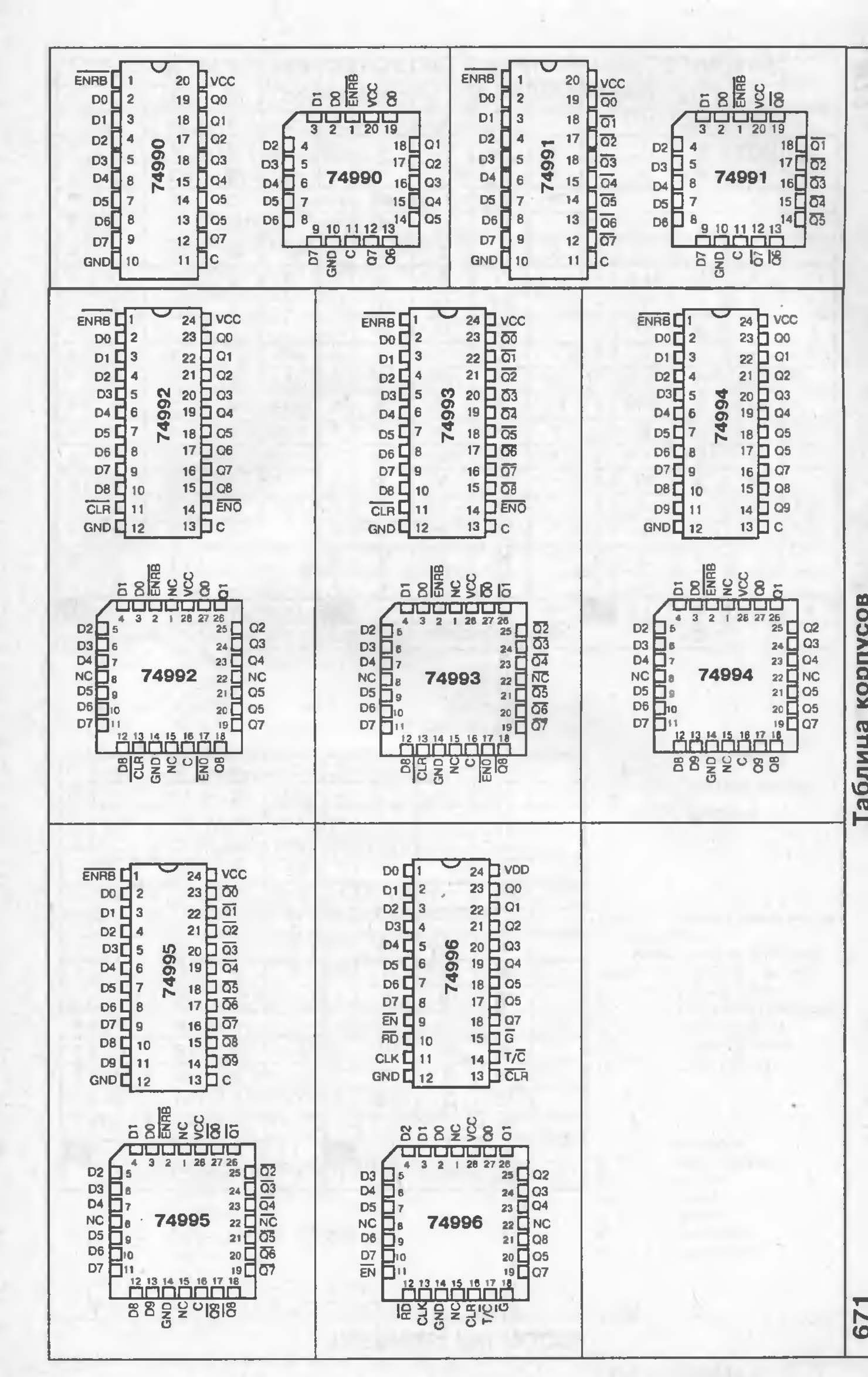

7486
1A 1B 1Q 2A 2B 2Q GND VCC 4A 4B 4Q 3A 3B 3Q
7486
1B 1A NC VCC 4A 1Q NC 2A NC 2B 4B NC 4Q NC 3A 2Q GND NC 3Q 3B
7486/1
1A 1B 1Q 2A 2B 2Q GND VCC 4A 4B 4Q 3A 3B 3Q
7486/1
1B 1A NC VDD 4A 1Q NC 2A NC 2B 4B NC 4Q NC 3A 2Q GND NC 3Q 3B
7466/2
1A 1B 1Q 2Q 2B 2A GND VCC 4A 4B 4Q 3Q 3B 3A
7486/3
1Q 1B 1A VCC 2A 2B 2Q 4Q 4B 4A GND 3A 3B 3Q
74861
GBA A0 A1 A2 A3 A4 A5 A6 A7 A6 A9 GND VCC B0 B1 B2 B3 B4 B5 B6 B7 B8 B9 GAB
74862
GBA A0 A1 A2 A3 A4 A6 A6 A7 A8 A9 GND VCC B0 B1 B2 B3 B4 B5 B6 B7 B8 B9 GAB
74863
GBA0 A0 A1 A2 A3 A4 A5 A6 A7 A8 GBA1 GND VCC B0 B1 B2 B3 B4 B5 B6 B7 B8 GAB0 GAB1
74864
GBA0 A0 A1 A2 A3 A4 A5 A6 A7 A9 GBA1 GND VCC B0 B1 B2 B3 B4 B5 B8 B7 B8 GAB0 GAB1
74866
ENL Q L/A P<Qin P>Qin Q7 Q5 Q5 Q4 Q3 Q2 Q1 Q0 P=Qout GND VCC CLR Q ENL P P7 P6 P5 P4 P3 P2 P1 P0 P<Qout P>Qout END
74866
P>Qin P<Qin L/A ENL Q VCC CLR Q ENL P Q7 Q6 Q5 Q4 Q3 Q2 Q1 P7 P6 P5 P4 P3 P2 P1 Q0 P=Qout GND ENO P>Qout P<Qout P0
74667
S0 S1 D0 D1 D2 D3 D4 D5 D6 D7 ENT GND VCC ENP Q0 Q1 Q2 Q3 Q4 Q5 Q6 Q7 CLK RC0
74867
D0 S1 S0 NC VCC ENP Q0 D1 D2 D3 NC D4 D5 D6 Q1 Q2 Q3 NC Q4 Q5 Q6 D7 ENT GND NC RC0 CLK Q7
74869
S0 S1 D0 D1 D2 D3 D4 D5 D6 D7 ENT GND VCC ENP Q0 Q1 Q2 Q3 Q4 Q5 Q6 Q7 CLK RC0
74869
D0 S1 S0 NC VCC ENP Q0 D1 D2 D3 NC D4 D5 D8 Q1 Q2 Q3 NC Q4 Q5 Q6 D7 ENT GND NC RC0 CLK Q7
7487
C A0 Q0 NC A1 Q1 GND VCC A3 Q3 NC A2 Q2 B
74870
S0 1A0 1A1 1A2 1A3 1R/W S2 DA0 DA1 DA2 DA3 GND VCC S1 2A3 2A2 2A1 2A0 2R/W S3 DB3 DB2 DB1 DB0
74870
1A1 1A0 S0 NC VCC S1 2A3 1A2 1A3 1R/W NC S2 DA0 DA1 2A2 2A1 2A0 NC 2R/W S3 DB3 DA2 DA3 GND NC DB0 DB1 DB2


74871
DA0 1, DA1 2, S0 3, 1A0 4, 1A1 5, 1A2 6, 1A3 7, 1R/W 8, S2 9, QA0 10, QA1 11, QA2 12, QA3 13, GND 14
28 VCC, 27 DA3, 26 DA2, 25 S1, 24 2A3, 23 2A2, 22 2A1, 21 2A0, 20 2R/W, 19 S3, 18 I/OB3, 17 I/OB2, 16 I/OB1, 15 I/OB0
74871
1A0 4, S0 3, DA1 2, DA0 1, VCC 28, DA3 27, DA2 26
1A1 5, 1A2 6, 1A3 7, 1R/W 8, S2 9, QA0 10, QA1 11
25 S1, 24 2A3, 23 2A2, 22 2A1, 21 2A0, 20 2R/W, 19 S3
QA2 12, QA3 13, GND 14, I/OB0 15, I/OB1 16, I/OB2 17, I/OB3 18
74873
1CLR 1, 1EN0 2, 1D0 3, 1D1 4, 1D2 5, 1D3 6, 2D0 7, 2D1 8, 2D2 9, 2D3 10, 2EN0 11, GND 12
24 VCC, 23 1ENL, 22 1Q0, 21 1Q1, 20 1Q2, 19 1Q3, 18 2Q0, 17 2Q1, 16 2Q2, 15 2Q3, 14 2ENL, 13 2CLR
74873
1D0 4, 1EN0 3, 1CLR 2, NC 1, VCC 26, 1ENL 27, 1Q0 26
1D1 5, 1D2 6, 1D3 7, NC 8, 2D0 9, 2D1 10, 2D2 11
25 1Q1, 24 1Q2, 23 1Q3, 22 NC, 21 2Q0, 20 2Q1, 19 2Q2
2D3 12, 2EN0 13, GND 14, NC 15, 2CLR 16, 2ENL 17, 2Q3 18
74874
1CLR 1, 1EN0 2, 1D0 3, 1D1 4, 1D2 5, 1D3 6, 2D0 7, 2D1 8, 2D2 9, 2D3 10, 2EN0 11, GND 12
24 VCC, 23 1CLK, 22 1Q0, 21 1Q1, 20 1Q2, 19 1Q3, 18 2Q0, 17 2Q1, 16 2Q2, 15 2Q3, 14 2CLK, 13 2CLR
74874
1D0 4, 1EN0 3, 1CLR 2, NC 1, VCC 28, 1CLK 27, 1Q0 26
1D1 5, 1D2 6, 1D3 7, NC 8, 2D0 9, 2D1 10, 2D2 11
25 1Q1, 24 1Q2, 23 1Q3, 22 NC, 21 2Q0, 20 2Q1, 19 2Q2
2D3 12, 2EN0 13, GND 14, NC 15, 2CLR 16, 2CLK 17, 2Q3 18
74876
1CLR 1, 1EN0 2, 1D0 3, 1D1 4, 1D2 5, 1D3 6, 2D0 7, 2D1 8, 2D2 9, 2D3 10, 2EN0 11, GND 12
24 VCC, 23 1CLK, 22 1Q0, 21 1Q1, 20 1Q2, 19 1Q3, 18 2Q0, 17 2Q1, 16 2Q2, 15 2Q3, 14 2CLK, 13 2CLR
74876
1D0 4, 1EN0 3, 1CLR 2, NC 1, VCC 26, 1CLK 27, 1Q0 26
1D1 5, 1D2 6, 1D3 7, NC 8, 2D0 9, 2D1 10, 2D2 11
25 1Q1, 24 1Q2, 23 1Q3, 22 NC, 21 2Q0, 20 2Q1, 19 2Q2
2D3 12, 2EN0 13, GND 14, NC 15, 2CLR 16, 2CLK 17, 2Q3 18
74877
S0 1, S1 2, S2 3, A0 4, A1 5, A2 6, A3 7, A4 8, A5 9, A6 10, A7 11, GND 12
24 VCC, 23 CLK, 22 DS, 21 B0, 20 B1, 19 B2, 18 B3, 17 B4, 16 B5, 15 B6, 14 B7, 13 QS
74877
S2 4, S1 3, S0 2, NC 1, VCC 28, CLK 27, DS 26
A0 5, A1 6, A2 7, NC 8, A3 9, A4 10, A5 11
25 B0, 24 B1, 23 B2, 22 NC, 21 B3, 20 B4, 19 B5
A6 12, A7 13, GND 14, NC 15, QS 16, B7 17, B6 18
74878
1CLR 1, 1EN0 2, 1D0 3, 1D1 4, 1D2 5, 1D3 6, 2D0 7, 2D1 8, 2D2 9, 2D3 10, 2EN0 11, GND 12
24 VCC, 23 1CLK, 22 1Q0, 21 1Q1, 20 1Q2, 19 1D3, 18 2Q0, 17 2Q1, 16 2Q2, 15 2Q3, 14 2CLK, 13 2CLR
74878
1D0 4, 1EN0 3, 1CLR 2, NC 1, VCC 28, 1CLK 27, 1Q0 26
1D1 5, 1D2 6, 1D3 7, NC 8, 2D0 9, 2D1 10, 2D2 11
25 1Q1, 24 1Q2, 23 1Q3, 22 NC, 21 2Q0, 20 2Q1, 19 2Q2
2D3 12, 2EN0 13, GND 14, NC 15, 2CLR 16, 2CLK 17, 2Q3 18
74879
1CLR 1, 1EN0 2, 1D0 3, 1D1 4, 1D2 5, 1D3 6, 2D0 7, 2D1 8, 2D2 9, 2D3 10, 2EN0 11, GND 12
24 VCC, 23 1CLK, 22 1Q0, 21 1Q1, 20 1Q2, 19 1Q3, 18 2Q0, 17 2Q1, 16 2Q2, 15 2Q3, 14 2CLK, 13 2CLR
74879
1D0 4, 1EN0 3, 1CLR 2, NC 1, VCC 28, 1CLK 27, 1Q0 28
1D1 5, 1D2 6, 1D3 7, NC 8, 2D0 9, 2D1 10, 2D2 11
25 1Q1, 24 1Q2, 23 1Q3, 22 NC, 21 2Q0, 20 2Q1, 19 2Q2
2D3 12, 2EN0 13, GND 14, NC 15, 2CLR 16, 2CLK 17, 2Q3 18
7488
Q0 1, Q1 2, Q2 3, Q3 4, Q4 5, Q5 6, Q6 7, GND 8
16 VCC, 15 CE, 14 A4, 13 A3, 12 A2, 11 A1, 10 A0, 9 Q7


74880
1S 1 24 VCC
1ENO 2 23 1ENL
1D0 3 22 1Q0
1D1 4 21 1Q1
1D2 5 20 1Q2
1D3 6 19 1Q3
2D0 7 16 2Q0
2D1 8 17 2Q1
2D2 9 16 2Q2
2D3 10 15 2Q3
2ENO 11 14 2ENL
GND 12 13 2S
74881
B0 1 24 VCC
A0 2 23 A1
S3 3 22 B1
S2 4 21 A2
S1 5 20 B2
S0 6 19 A3
CYn 7 16 B3
BA 8 17 G
Q0 9 16 CYn+4
Q1 10 15 P
Q2 11 14 A=B
GND 12 13 Q3
74882
CYn 1 24 VCC
G0 2 23 NC
P0 3 22 CYn+32
G1 4 21 P7
P1 5 20 G7
CYn+4 6 19 P6
G2 7 16 G6
P2 8 17 CYn+24
G3 9 16 P5
P3 10 15 G5
CYn+16 11 14 P4
GND 12 13 G4
74885
L/A 1 24 VCC
A<Bin 2 23 ENL P
A>Bin 3 22 A7
B7 4 21 A6
B6 5 20 A5
B5 6 19 A4
B4 7 16 A3
B3 8 17 A2
B2 9 16 A1
B1 10 15 A0
B0 11 14 A<Bout
GND 12 13 A>Bout
74880
1D0 1ENO 1S NC VCC 1ENL 1Q0
4 3 2 1 26 27 26
1D1 5 25 1Q1
1D2 6 24 1Q2
1D3 7 23 1Q3
NC 8 22 NC
2D0 9 21 2Q0
2D1 10 20 3Q1
2D2 11 19 2Q2
12 13 14 15 16 17 18
2D3 2ENO GND NC 2S 2ENL 2Q3
74882
P0 G0 CYn NC VCC NC CYn+32
4 3 2 1 26 27 26
G1 5 25 P7
P1 6 24 G7
CYn+8 7 23 P6
NC 8 22 NC
G2 9 21 G6
10 20 CYn+24
P2 11 19 P5
G3
12 13 14 15 16 17 18
P3 CYn+16 GND NC G4 P4 G5
74885
A>Bin A<Bin L/A NC VCC ENL P A7
4 3 2 1 26 27 26
B7 5 25 A6
B6 6 24 A5
B5 7 23 A4
NC 6 22 NC
B4 9 21 A3
B3 10 20 A2
B2 11 19 A1
12 13 14 15 16 17 18
B1 B0 GND NC A>Bout A<Bout A0
7489
A0 1 16 VCC
CE 2 15 A1
WR 3 14 A2
D0 4 13 A3
Q0 5 12 D3
D1 6 11 Q3
Q1 7 10 D2
GND 8 9 Q2
748960
VCC 1 28 ENL
ENO A 2 27 B0
A0 3 26 B1
GND 4 25 GND
A1 5 24 B2
A2 6 23 B3
A3 7 22 GND
GND 6 21 B4
A4 9 20 B5
A5 10 19 B6
GND 11 18 GND
A6 12 17 B7
A7 13 16 ENO B1
Vx 14 15 ENO B0
748961
VCC 1 28 ENL
ENO A 2 27 B0
A0 3 26 B1
GND 4 25 GND
A1 5 24 B2
A2 6 23 B3
A3 7 22 GND
GND 8 21 B4
A4 9 20 B5
A5 10 19 B6
GND 11 18 GND
A6 12 17 B7
A7 13 16 ENO B1
Vx 14 15 ENO B0
74899
ODD/EVEN 1 28 VCC
ERR A 2 27 GAB
ENL A 3 26 B0
A0 4 25 B1
A1 5 24 B2
A2 6 23 B3
A3 7 22 B4
A4 6 21 B5
A5 9 20 B6
A6 10 19 B7
A7 11 18 PAR B
PAR A 12 17 ENL B
GBA 13 16 SEL
GND 14 15 ERR B
748960
GND A0 ENO A VCC ENL B0 B1
4 3 2 1 28 27 28
A1 5 25 GND
A2 6 24 B2
A3 7 23 B3
GND 8 22 GND
A4 9 21 B4
A5 10 20 B5
GND 11 19 B6
12 13 14 15 16 17 18
A6 A7 Vx END B0 END B1 B7 GND
748961
GND A0 END A VCC ENL B0 B1
4 3 2 1 28 27 26
A1 5 25 GND
A2 6 24 B2
A3 7 23 B3
GND 8 22 GND
A4 9 21 B4
A5 10 20 B5
GND 11 19 B6
12 13 14 15 16 17 18
A6 A7 Vx ENO B0 ENO B1 B7 GND
74899
A0 ENL A ERR A ODD/EVEN VCC GAB B0
4 3 2 1 28 27 28
A1 5 25 B1
A2 6 24 B2
A3 7 23 B3
A4 8 22 B4
A5 9 21 B5
A6 10 20 B6
A7 11 19 B7
12 13 14 15 16 17 18
PAR A GBA GND ERR B SEL ENL B PAR B
7490
B 1 14 A
RO1 2 13 NC
RO2 3 12 Q0
NC 4 11 Q3
VCC 5 10 GND
S91 6 9 Q1
S92 7 6 Q2
7490
RO1 B NC A NC
3 2 1 20 19
RO2 4 16 Q0
NC 5 17 NC
NC 6 16 Q3
NC 7 15 NC
VCC 6 14 GND
9 10 11 12 13
S91 S92 NC Q2 Q1
749014
A1 1 20 VCC
A2 2 19 Q1
A3 3 18 Q2
A4 4 17 Q3
A5 5 16 Q4
A6 6 15 Q5
A7 7 14 Q6
A8 8 13 Q7
A9 9 12 Q6
GND 10 11 Q9
749015
A1 1 20 VCC
A2 2 19 Q1
A3 3 16 Q2
A4 4 17 Q3
A5 5 16 Q4
A6 6 15 Q5
A7 7 14 Q6
A8 6 13 Q7
A9 9 12 Q8
GND 10 11 Q9


7491
NC 1, NC 2, NC 3, NC 4, VCC 5, NC 6, NC 7, NC 8, CLK 9, GND 10, B 11, A 12, Q 13, Q̄ 14
7491/1
NC 1, NC 2, NC 3, NC 4, VCC 5, NC 6, NC 7, NC 8, CLK 9, GND 10, B 11, A 12, Q 13, Q̄ 14
7491/1
NC 1, NC 2, NC 3, NC 4, NC 5, NC 6, NC 7, VCC 8, NC 9, NC 10, NC 11, NC 12, CLK 13, GND 14, NC 15, B 16, NC 17, A 18, Q 19, Q̄ 20
7491/2
NC 1, NC 2, NC 3, VCC 4, NC 5, NC 6, NC 7, QS 8, CLK 9, A 10, GND 11, B 12, Q 13, Q̄ 14
749114
A1 1, A2 2, A3 3, A4 4, A5 5, A6 6, A7 7, A8 8, A9 9, GND 10, Q̄9 11, Q̄8 12, Q̄7 13, Q̄6 14, Q̄5 15, Q̄4 16, Q̄3 17, Q̄2 18, Q̄1 19, VCC 20
749115
A1 1, A2 2, A3 3, A4 4, A5 5, A6 6, A7 7, A8 8, A9 9, GND 10, Q9 11, Q8 12, Q7 13, Q6 14, Q5 15, Q4 16, Q3 17, Q2 18, Q1 19, VCC 20
7492
B 1, NC 2, NC 3, NC 4, VCC 5, RO1 6, RD2 7, Q3 8, Q2 9, GND 10, Q1 11, Q0 12, NC 13, A 14
7492
NC 1, B 2, NC 3, NC 4, NC 5, NC 6, NC 7, VCC 8, RO1 9, RO2 10, NC 11, Q3 12, Q2 13, GND 14, NC 15, Q1 16, NC 17, Q0 18, NC 19, A 20
7493
B 1, RD1 2, RO2 3, NC 4, VCC 5, NC 6, NC 7, Q2 8, Q1 9, GND 10, Q3 11, Q0 12, NC 13, A 14
7493/1
B 1, RD1 2, RO2 3, NC 4, VCC 5, NC 6, NC 7, Q2 8, Q1 9, GND 10, Q3 11, Q0 12, NC 13, A 14
7493/1
NC 1, B 2, RO1 3, RO2 4, NC 5, NC 6, NC 7, VCC 8, NC 9, NC 10, NC 11, Q2 12, Q1 13, GND 14, NC 15, Q3 16, NC 17, Q0 18, NC 19, A 20
7493/2
RD1 1, RD2 2, NC 3, VCC 4, NC 5, NC 6, NC 7, B 8, Q1 9, Q2 10, GND 11, Q3 12, Q0 13, A 14
7494
A0 1, A1 2, A2 3, A3 4, VCC 5, S1 6, DS 7, CLK 8, QS 9, CLR 10, B3 11, GND 12, B2 13, B1 14, S2 15, B0 16
74940
EN̄1 1, D0 2, Q̄7 3, D1 4, Q̄6 5, D2 6, Q̄5 7, D3 8, Q̄4 9, GND 10, D4 11, Q̄3 12, D5 13, Q̄2 14, D6 15, Q̄1 16, D7 17, Q̄0 18, EN̄2 19, VCC 20
74941
EN̄1 1, D0 2, Q7 3, D1 4, Q6 5, D2 6, Q5 7, D3 8, Q4 9, GND 10, D4 11, Q3 12, D5 13, Q2 14, D6 15, Q1 16, D7 17, Q0 18, EN̄2 19, VCC 20
7495
DS 1, D0 2, D1 3, D2 4, D3 5, MC 6, GND 7, CLKL 8, CLKR 9, Q3 10, Q2 11, Q1 12, Q0 13, VCC 14
7495/1
DS 1, D0 2, D1 3, D2 4, D3 5, MC 6, GND 7, CLKL 8, CLKR 9, Q3 10, Q2 11, Q1 12, Q0 13, VCC 14
7495/1
NC 1, DS 2, D0 3, D1 4, NC 5, D2 6, NC 7, D3 8, MC 9, GND 10, NC 11, CLKL 12, CLKR 13, Q3 14, NC 15, Q2 16, NC 17, Q1 18, Q0 19, VCC 20
7495/2
SE 1, D1 2, D2 3, VCC 4, D3 5, MC 6, CLKR 7, CLKL 8, Q3 9, Q2 10, GND 11, Q1 12, Q0 13, D0 14
74952
DISO 1, DS 2, DISI 3, DISTU 4, DISTD 5, DISS 6, QS 7, CLK 8, GND 9, I/O7 10, I/O6 11, I/O5 12, I/O4 13, I/O3 14, I/O2 15, I/O1 16, I/O0 17, VCC 18
Connections:
DISI input disable
DISTU transfer up disable
DISTD transfer down disable
DISS shift disable
DISO output disable


7496
CLK 1 16 CLR
A 2 15 Q0
B 3 14 Q1
C 4 13 Q2
VCC 5 12 GND
D 6 11 Q3
E 7 10 Q4
S 8 9 DS
7496
A 3, CLK 2, NC 1, CLR 20, Q0 19
B 4, C 5, NC 6, VCC 7, D 8
18 Q1, 17 Q2, 16 NC, 15 GND, 14 Q3
E 9, S 10, NC 11, DS 12, QS 13
74962
DISO 1 16 VCC
DS 2 17 I/O0
DISI 3 18 I/O1
DISTU 4 15 I/O2
DISTD 5 14 I/O3
DISS 6 13 I/O4
QS 7 12 I/O5
CLK 8 11 I/O6
GND 9 10 I/O7
Connections:
DISI input disable
DISTU transfer up disable
DISTD transfer down disable
DISS shift disable
DISO output disable
74963
EN0 1 20 VCC
DS 2 19 I/O0
EN1 3 18 I/O1
G2-1 4 17 I/O2
SCLR 5 16 I/O3
G1-2 6 15 I/O4
ENSH 7 14 I/O5
QS 8 13 I/O6
CLK2 9 12 I/O7
GND 10 11 CLK1
74963
EN1 3, DS 2, EN0 1, VCC 20, I/O0 19
G2-1 4, SCLR 5, G1-2 6, ENSH 7, QS 8
18 I/O1, 17 I/O2, 16 I/O3, 15 I/O4, 14 I/O5
CLK2 9, GND 10, CLK1 11, I/O7 12, I/O6 13
74964
EN0 1 20 VCC
DS 2 19 I/O0
EN1 3 18 I/O1
G2-1 4 17 I/O2
SCLR 5 16 I/O3
G1-2 6 15 I/O4
ENSH 7 14 I/O5
QS 8 13 I/O6
CLK 9 12 I/O7
GND 10 11 ACLR
74964
EN1 3, DS 2, EN0 1, VCC 20, I/O0 19
G2-1 4, SCLR 5, G1-2 6, ENSH 7, QS 8
18 I/O1, 17 I/O2, 16 I/O3, 15 I/O4, 14 I/O5
CLK 9, GND 10, ACLR 11, I/O7 12, I/O6 13
74968
Q0 7, Q1 6, Q2 5, Q3 4, Q4 3, GND TTL 2, OE 1, VCC TTL 52, VCC ECL 51, Q5 50, Q6 49, Q7 48, Q8 47
CAS1 8, RAS1 9, CAS0 10, RAS0 11, CAS1 12, CS 13, MSEL 14, AR0 15, AC0 16, AR1 17, AC1 18, AR2 19, AC2 20
46 Q9, 45 RAS2, 44 CAS2, 43 RAS3, 42 CAS3, 41 RAS1, 40 MC0, 39 MC1, 38 SEL1, 37 SEL0, 36 AC9, 35 AR9, 34 AC8
AR3 21, AC3 22, AR4 23, AC4 24, GND ECL 25, LE 26, AR5 27, AC5 28, AR6 29, AC6 30, AR7 31, AC7 32, AR8 33
Connections:
AC0...AC9 column address inputs
AR0...AR9 row address inputs
MC0, MC1 mode control inputs
CS chip select
MSEL multiplexer select input
LE latch enable
SEL0...SEL3 bank select
RAS1, CAS1 Row/column address strobe
OE output enable
RAS0...RAS3 row address strobe outputs
CAS0...CAS3 columns address strobe outputs
Q0...Q9 address outputs
74968
CS 1 52 CAS1
MSEL 2 51 RAS0
AR0 3 50 CAS0
AC0 4 49 RAS1
AR1 5 48 CAS1
AC1 6 47 Q0
AR2 7 46 Q1
AC2 8 45 Q2
AR3 9 44 Q3
AC3 10 43 Q4
AR4 11 42 GND TTL
AC4 12 41 OE
GND ECL 13 40 VCC TTL
LE 14 39 VCC ECL
AR5 15 38 Q5
AC5 16 37 QS
AR6 17 36 Q7
AC6 18 35 Q8
AR7 19 34 Q9
AC7 20 33 RAS2
AR8 21 32 CAS2
AC8 22 31 RAS3
AR9 23 30 CAS3
AC9 24 29 RASI
SEL0 25 28 MC0
SEL1 26 27 MC1
7497
B 1 16 VCC
E 2 15 D
F 3 14 C
A 4 13 CLR
Q 5 12 CASCI
CASCO 6 11 EN1
EN0 7 10 STR
GND 8 9 CLR
74978
EN0 1 24 VDD
MODE 2 23 TCLK
D0 3 22 Q0
D1 4 21 Q1
D2 5 20 Q2
D3 6 19 Q3
D4 7 18 Q4
D5 8 17 Q5
DS 9 16 QS
D7 10 15 Q7
SD1 11 14 SD0
GND 12 13 DCLK
74978
D0 4, MODE 3, EN0 2, NC 1, VCC 28, VC 27, TCLK 26
D1 5, D2 6, D3 7, D4 8, D5 9, D6 10, D7 11
25 Q0, 24 Q1, 23 Q2, 22 Q3, 21 Q4, 20 Q5, 19 Q6
SD1 12, GND 13, GND 14, NC 15, DCLK 16, SD0 17, Q7 18
7498
A2 1 16 VCC
A1 2 15 Q0
B1 3 14 Q1
B2 4 13 Q2
C1 5 12 D1
C2 6 11 Q3
D2 7 10 CLK
GND 8 9 W
7499
D0 1 16 K
J 2 15 Q0
D1 3 14 Q1
D2 4 13 GND
VCC 5 12 Q2
D3 6 11 Q3
MC 7 10 Q3
CLKR 8 9 CLKL


74990
ENRB 1 20 VCC
D0 2 19 Q0
D1 3 18 Q1
D2 4 17 Q2
D3 5 18 Q3
D4 8 15 Q4
D5 7 14 Q5
D6 8 13 Q5
D7 9 12 Q7
GND 10 11 C
74990
D1 D0 ENRB VCC Q0
3 2 1 20 19
D2 4 18 Q1
D3 5 17 Q2
D4 6 16 Q3
D5 7 15 Q4
D6 8 14 Q5
9 10 11 12 13
D7 GND C Q7 Q6
74991
ENRB 1 20 VCC
D0 2 19 Q0
D1 3 18 Q1
D2 4 17 Q2
D3 5 18 Q3
D4 6 15 Q4
D5 7 14 Q5
D6 8 13 Q6
D7 9 12 Q7
GND 10 11 C
74991
D1 D0 ENRB VCC Q0
3 2 1 20 19
D2 4 18 Q1
D3 5 17 Q2
D4 8 16 Q3
D5 7 15 Q4
D6 8 14 Q5
9 10 11 12 13
D7 GND C Q7 Q6
74992
ENRB 1 24 VCC
D0 2 23 Q0
D1 3 22 Q1
D2 4 21 Q2
D3 5 20 Q3
D4 6 19 Q4
D5 7 18 Q5
D6 8 17 Q6
D7 9 16 Q7
D8 10 15 Q8
CLR 11 14 ENO
GND 12 13 C
74992
D1 D0 ENRB NC VCC Q0 Q1
4 3 2 1 28 27 26
D2 5 25 Q2
D3 6 24 Q3
D4 7 23 Q4
NC 8 22 NC
D5 9 21 Q5
D6 10 20 Q5
D7 11 19 Q7
12 13 14 15 16 17 18
D8 CLR GND NC C ENO Q8
74993
ENRB 1 24 VCC
D0 2 23 Q0
D1 3 22 Q1
D2 4 21 Q2
D3 5 20 Q3
D4 6 19 Q4
D5 7 18 Q5
D6 8 17 Q6
D7 9 16 Q7
D8 10 15 Q8
CLR 11 14 ENO
GND 12 13 C
74993
D1 D0 ENRB NC VCC Q0 Q1
4 3 2 1 28 27 26
D2 5 25 Q2
D3 6 24 Q3
D4 7 23 Q4
NC 8 22 NC
D5 9 21 Q5
D6 10 20 Q6
D7 11 19 Q7
12 13 14 15 16 17 18
D8 CLR GND NC C ENO Q8
74994
ENRB 1 24 VCC
D0 2 23 Q0
D1 3 22 Q1
D2 4 21 Q2
D3 5 20 Q3
D4 6 19 Q4
D5 7 18 Q5
D6 8 17 Q5
D7 9 16 Q7
D8 10 15 Q8
D9 11 14 Q9
GND 12 13 C
74994
D1 D0 ENRB NC VCC Q0 Q1
4 3 2 1 28 27 26
D2 5 25 Q2
D3 6 24 Q3
D4 7 23 Q4
NC 8 22 NC
D5 9 21 Q5
D6 10 20 Q5
D7 11 19 Q7
12 13 14 15 16 17 18
D8 D9 GND NC C Q9 Q8
74995
ENRB 1 24 VCC
D0 2 23 Q0
D1 3 22 Q1
D2 4 21 Q2
D3 5 20 Q3
D4 6 19 Q4
D5 7 18 Q5
D6 8 17 Q6
D7 9 16 Q7
D8 10 15 Q8
D9 11 14 Q9
GND 12 13 C
74995
D1 D0 ENRB NC VCC Q0 Q1
4 3 2 1 28 27 26
D2 5 25 Q2
D3 6 24 Q3
D4 7 23 Q4
NC 8 22 NC
D5 9 21 Q5
D6 10 20 Q6
D7 11 19 Q7
12 13 14 15 16 17 18
D8 D9 GND NC C Q9 Q8
74996
D0 1 24 VDD
D1 2 23 Q0
D2 3 22 Q1
D3 4 21 Q2
D4 5 20 Q3
D5 6 19 Q4
D6 7 18 Q5
D7 8 17 Q5
EN 9 18 Q7
RD 10 15 G
CLK 11 14 T/C
GND 12 13 CLR
74996
D2 D1 D0 NC VCC Q0 Q1
4 3 2 1 28 27 26
D3 5 25 Q2
D4 6 24 Q3
D5 7 23 Q4
NC 8 22 NC
D6 9 21 Q8
D7 10 20 Q5
EN 11 19 Q7
12 13 14 15 16 17 18
RD CLK GND NC CLR T/C G

ТАБЛИЦЫ PIN-КОДОВ

C............ Коллектор
E............ Эмиттер
B............ База
A............ Анод
K............ Катод
G............ Управляющий электрод

Полевые транзисторы

	1	2	3	4
a	S	G	D	
b	S	D	G	
c	G	D	S	
d	G	S	D	
e	D	G	S	
f	D	S	G	
g	G1	G2	D	S
h	D	G2	G1	S
j	S	D	G	D
k	S	D	G	Sub
l	S	D	G2	G1
m	D	S	G	Sub
n	S	G	D	Sub
o	S	G1	D	G2
p	G	D	S	D

Однопереходный транзистор

	1	2	3	4
a	B1		B2	E
b	B2	E	B1	
c	B1	E	B2	
d	B1	B2	E	
e	E	B1		B2
f	E	B1	B2	
g	E	B2	B1	
h	B2	B1	E	
j				
k				
l				
m				
n				
o				
p				

D............ Сток (Drain)
S............ Исток (Sourse)
G............ Затвор (Gate)
B............ Подложка (Substrate)
K............ Корпус (Case)
Sub......... Substrate - Вывод может быть использован затвором
Geh......... Паять к поверхности

° .... Двойной
* .... Четыре вывода
** .... Иногда без второго вывода

Транзисторы + дарлингтон

	1	2	3	4
a	E	B	C	
b	E	C	B	
c	B	C	E	
d	B	E	C	
e	C	B	E	
f	C	E	B	
g	E	B	C	Geh
h	E	C	B	C
j	B	C	E	C
k	B	E	C	Geh
l				
m	E	B	C	C
n	C	B	E	C
o	C	B	E	B
p	E	B	C	B
q	B	E	C	E
r	E	C	E	B
s	E	B	E	C
t	B	E	B	C
u	C	E	B	E
v	B	C	B	E

Тиристор, симистор, тетрод

	1	2	3	4
a	K	G	A	
b	K	A	G	
c	G	A	K	
d	A	K	G	
e	K	A	G	A
f	G	(A)**	K	A
g	K	Gk	Ga	A
h	K	Gk	A	Ga
j	A1	A2	G	A2
k	K		G	A
l	A1	A2	G	
m	A1	G	A2	
n	A	G	K	
o	K	G	A	A
p	A2	G	A1	
q	A1	G	A2	A2
r	A	K	G	A
s	K	Ga	Gk	A
t	G	K	A	
u	K		A	G
v	G	A1	A2	

Диод

	1	2	3	4
a	A	K		
b	K	A		
c	A		K	(K)*
d	K		A	(A)*
e	A2	K	A1	
f	A(1)	A(2)	K	
g	A	K(1)	K(2)	
h	K(1)	A	K(2)	
j	A(1)	K	A(2)	
k	K		A	K
l	A2	A1		
m	A		K	A
n	K(1)	K(2)	A	
o				
p		A	K	
q		K	A	
r	A1	A2/K1	K2	
s	A1	K2	A2/K1	
t	K1	A2	A1/K2	
u	K1	A1/K2	A2	
v				

СПИСОК ПРОИЗВОДИТЕЛЕЙ ЭЛЕКТРОННЫХ ПРИБОРОВ, ПРИВЕДЕННЫХ В СПРАВОЧНИКЕ

Adv	Advanced Research Association
Aeg	Temic Telefunken
Alp	Alpha industries Inc.
Amc, Amp	Ampower Semicon Corp.
Bbc	BBC Brown Bovery Ltd
Ben	Bendix Semicon. Products
Bog	Bogue Electric Manufacturing
Cbs	Cbs Electronics
Cen	Harris (GE) Transistor
Clv	Clevite Tpansistor
Cod	CODI Corp.
Cri	Crimson Semicon. Inc.
Csr	Csr Industries Inc.
Ctr	Acrian Inc.
Del	Delco Electronics
Dio	Dionics Inc.
Edl	EDAL Industries
Etc	Electronic Transistor Corporation
EUR	Европейские производители
Fag	Fagor Electrotecnica S. Corp.
Fch	Fairchild Simicon.
Fer	Ferranti Gmbh
Fjd	Fuji Denki Seizo Com.
Fsem	Semitronics Corporation
Fui	Fujitsu
Gdc	General Diode Corp.
Gen	Harris (General Electric Semicon)
Gie	General Instrument
Gpd	Germanium Power Devices Cor.
Gsi	General Semicon. Industries Inc.
Hew	Hewlett Packard
Hfo	Halbleiterwerk Frankfurt
Hit	Hitachi
Hug	Hughes Aircraft Company
Idc	International Diode Corporation
Idi	International Devices Inc.
Inr	International Rectifier Corp.
Itt	ITT
Jap	Японские производители
Kem	Kemtron Electron Product
Khe	KH-Electronics
Kmc	KMC-Semicon.
Ksw	KSW Electronics Cor.
Mal	Mallory Distributor Product Co
Mat	Matsushita
Mdc	Microwave Diode Corp.
Mic	Micro Electronic
Mit	Mitsubishi
Miv	Microwave Associates
Mot	Motorola
Msc	Microsemicon Cor.
Mws	Microwave Semicon. Corp.

СПИСОК ПРОИЗВОДИТЕЛЕЙ ЭЛЕКТРОННЫХ ПРИБОРОВ, ПРИВЕДЕННЫХ В СПРАВОЧНИКЕ

Nae NAE INC
Nec NEC
Nip О производителе нет данных
Njr New Japan Radio Co Ltd
Nsc National Semicon
Nth Herman Khler Electric Gmdh&Co
Oki OKI Semicon
old О производителе нет данных, приборы сняты с производства
Org Original Electronic Co Ltd
Pai Parametric Ind. Inc.
Phc Philco Corp.
Ppc PPC Products Corp.
Ray Raytheon Halbleiter Gmbh
Rca RCA
Rhm ROHM
Sak Sanken Electric Co Ltd
Say Sanyo
Sca Semicoa
Scn Semicon Components inc.
Sem Semitronics Corp.
Sgs SGS-Thomson
Shi Shindengen Electronic Co Ltd
Sie Siemens AG
Six Siliconics GmbH
Sol Solitron Devices Inc.
Son Sony
Spe Space Power Electronic Inc.
Spr Sprague Electric
Ssc SSC Silec - Semi - Conductors
Ssi Solid State Devices
Stc Silicon Transistor Corp.
Stl Stanley Electric Co
Sty О производителе нет данных
Syl Sylvania Semicon
Sym Symbol Semicon
Tag TAG Semicon
TDY TELEDYNE Components
Tho Thomson
Tis Texas Instruments
Tix Texas Instruments
Tos Toshiba
Tra Transitron Electronic Corp.
Trw TRW Vertiebs CmbH
Tsc Teledyne Semicon.
Tun Tung-Sol Electric
Uni Unitrode Corporation
Unz Unizon
Upi UPI Semicon
USA Различные производители США
Usr v/o Electronzagranpostavka
Wes Western Electric Co
Whs Westinghouse Electric Cor.

СПИСОК WEB-АДРЕСОВ ФИРМ-ПРОИЗВОДИТЕЛЕЙ ЭЛЕКТРОННЫХ ПОЛУПРОВОДНИКОВЫХ ПРИБОРОВ

Sanyo: http://www.semic.sanyo.co.jp/indexe.htm
Toshiba: http://doc.semicon.toshiba.co.jp/indexus.htm
NEC: www.nec.com
Hitachi: www.halsp.hitachi.com
Harris: www.semi.harris.com
Texas Instruments: www.ti.com
Motorola: www.mot.com
National Semiconductor: www.national.com
New Japan Radio Co Ltd: www.njr.com
Mitsubishi Electric: www.mitsubishi.com
Sony: www.sel.sony.com/s
Fujitsu Mikroelectronik: www.fmi.fujitsu.com
Oki: www.ok.com
SGS-THOMSON: www.st.com

ИДЕНТИФИКАЦИЯ ОСНОВНЫХ ФИРМ-ПРОИЗВОДИТЕЛЕЙ ПО ПРЕФИКСУ

Префикс	Фирма
A	Advanced Micro Devices Ailed co Microsystems
AD	Analog Devices Harris Semiconductor
ADC	National Semiconductor
ADEL	Analog Devices
ADG	Analog Devices
AOM	Analog Devices
ADS	Burr-Brown
ADVEC	Analog Devices
ALD	Burr-Brown
AM	Advanced Micro Devices
AMP	Analog Devices
AMPAL	Advanced Micro Devices
AMSREF	Advanced Monolithic
AN	Matsushita Electronic Components
AT	Atmel
ATT	Lucent Technologies
ATV	Atmel
AVS	STMicroelectronics
BA	Rohm
BQ	Benchmark
BU	Rohm
BUF	Analog Devices Burr- Brown
CA	Harris Semiconductor
CD	Harris Semiconductor Fairchild Semiconductor
CDP	Harris Semiconductor
CLC	National Semiconductor
CM	TEMIC
CMP	Analog Devices
COM	Standard Microsystems
COP	National Semiconductor
CP	Harris Semiconductor
CS	Harris Semiconductor Cherry Semiconductor
CX	Cyrix
CXA, CXD	Sony
CXK, CXP	Sony
CY	Cypress Semiconductor
D	Intel
DAC	Analog Devices National Semiconductor Burr-Brown
DBL	Daewoo Electronics Semiconductor
DCP	Burr-Brown
DG	Harris Semiconductor TEMIC
DM	Fairchild Semiconductor
DP	National Semiconductor
DS	Dalias Semiconductor National Semiconductor
EP	STmicroelectronics
EL	Elantec California Micro Devices
GAL	Lattice Semiconductor
GL	LG Semicon
GM	LG Semicon
GMM	LG Semicon
GSD	STMicroelectronics
H	Harris Semiconductor
HA	Harris Semiconductor Hitachi
HCF	STMicroelectronics
HCPL	Hewlett-Packard
HCTL	Hewlett-Packard
HD	Hitachi
HEF	Philips Semiconductor
HFA	Harris Semiconductor
HI	Harris Semiconductor
HIN	Harris Semiconductor
HIP	Harris Semiconductor
HM	TEMIC Hitachi
HPM	Hewlett-Packard
HT	Holtek Microelectronics
HV	Harris Semiconductor Supertex

ИДЕНТИФИКАЦИЯ ОСНОВНЫХ ФИРМ-ПРОИЗВОДИТЕЛЕЙ ПО ПРЕФИКСУ

Префикс	Фирма
HY	Hyundai
ICL	Harris Semiconductor
ICM	Harris Semiconductor
IDT	Integrated Device Technology
INA	Burr-Brown
IP	TEMIC
IR	International Rectifier
IS	ISSI Burr-Brown
ISO	Information Storage Devices
ISPLSI	Lattice Semiconductor
IVC	Burr- Brown
IX	Share
KA	Samsung Semiconductor
KIA	Korea Electronics (KEC)
KM	Samsung Semiconductor
KMM	Samsung Semiconductor
KR	Standard Microsystems STMicroelectronics Sanyo Unitrode
LA	Sanyo
LB	Sanyo
LC	Sanyo
LF	National Semiconductor Motorola
LH	National Semiconductor
LM	National Semiconductor STMicroelectronics
LMC	National Semiconductor
LMD	National Semiconductor
LMF	National Semiconductor
LMX	National Semiconductor
LP	National Semiconductor
LPC	National Semiconductor
LS	STMicroelectronics LSI Computer Systems
LTC	Linear Technology
LX	Linfinity Microelectronics
M	STMicroelectronics Mitsubishi Semiconductor

Префикс	Фирма
MAB	Philips Semiconductor
MACH	Vantis
MAX	Maxim
MB	Fujitsu
MBM Fujitsu	
MC	Motorola STMicroelectronics Texas Instruments
MCCS	Motorola
MCM	Motorola
MCT	Motorola
MCU	TT Semiconductors
MDA	TT Semiconductors
MF	National Semiconductor
MIC	Micrel Semiconductor
MK	STMicroelectronics
ML	Micro Linear
MM	Fairchild Semiconductor National Semiconductor
MN	Matsushlta Electronic Comoonents
MPC	Burr-Brown
MPY	Burr- Brown
MSC	DKJ Semiconductor
MSM	DKI Semiconductor
MSP	ITT Semiconductors
MT	Mitel Semiconductor
MUX	Analog Devices
MVA	GEC Plessev
MX	Macronix International Maxim
N	Philips Semlconductor Intel
NE	Philips Semiconductor Texas Instrumenls
NJM	NJR
NM	Hairchild Semiconductor
NSC	Newport Components
NMC	Fairchild Semiconductor
NQ	SEEQ Technology
DHN	Dptek Technology

ИДЕНТИФИКАЦИЯ ОСНОВНЫХ ФИРМ-ПРОИЗВОДИТЕЛЕЙ ПО ПРЕФИКСУ

Префикс	Фирма
OP	Analog Devices Texas Instruments
OPA	Burr-Brown
OPT	Burr-Brown
P	Intel TEMIC performance Semiconductor
PA	Intel Apex Microtechnology
PAL	Advanced Micro Devices
PALCE	Cypress Semiconductor Vantis
PEL	Ericsson
PC	Philips Semiconductor
PCD	Philips Semiconductor
PCF	Philips Semiconductor
PCM	Burr-Brown
PDM	Paradigm Technology
PGA	Burr-Brown
PH	Silicon Storage Technology
PIC	Microchip Technology
PLC	Philips Semiconductor
PLS	Philips Semiconductor
PLT	Linear Technology
PM	Analog Devices
PQ	SEEQ Technology
PSD	Waferscale Integration
PZ	Philips Semiconductor
QS	Quality Semiconductor
R	Rockwell Semiconductor Systems
RC	Ravtheon Semiconductor Texas Instruments
RCV	Burr-Brown
REF	Analog Devices Burr-Brown
REG	Burr-Brown
RTC	Seiko Epson
S	TEMIC Philips Semiconductor
SA	Philips Semiconductor
SAA	Philips Semiconductor ITT Semiconductors
SAB	Infineon Technologies Philips Semiconductor
SABC	Infineon Technologies
SC	Philips Semiconductor
SCC	Philips Semiconductor
SCN	Philips Semiconductor
SD	TEMIC
SDA	Infineon Technologies
SE	Philips Semiconductor STMicroelectronics
SG	Texas Instruments Infinity Microelectronics Motorola
SHC	Burr- Brown TEMIC
St	Maxim Sanken
SL	GEC Plessev
SM	Nippon Precision Circuits
SN	Texas Instruments Motorola
SS	Honeywell
SSM	Analog Devices
ST	STMicroelectronics
STK	Sanyo
STR	Altegro Microsystems
STRD	Sanken
STRF	Sanken
STRM	Sanken
STRS	Sanken
STV	STMicroeiectronics
SW	Analog Devices
TA	Toshiba
TBA	STMicroelectronics Infineon Technologies Philips Semiconductor Telefunken ITT Semiconductors
TBB	Infineon Technologies
TC	TelCom Semiconductor Toshiba
TCA	Motorola Infineon Technologies Philips Semiconductor

ИДЕНТИФИКАЦИЯ ОСНОВНЫХ ФИРМ-ПРОИЗВОДИТЕЛЕЙ ПО ПРЕФИКСУ

Префикс	Фирма
TCM	TelCom Semiconductor
TD	STMicroelectromcs Toshiba
TDA	Philips Semiconductor Motorola STMicroeiectronics Infineon Technologies ITT Semiconductors Telefunken
TDB	STMicroeiectronics
TDE	STMicroelectronics
TEA	Philips Semiconductor STMicroeiectronics Telefunken
THM	Toshiba
TIBPAL	Texas Instruments Texas Instruments
TL	STMicroelectronics Motorola
TLC	Texas Instruments
TLE	Texas Instruments
TM	Texas Instruments
TMC	Raytheon Semiconductor
TMP	Toshiba
TMPZ	Toshiba
TMS	Texas Instruments
TP	National Semiconductor
TPU	TT Semiconductors
TS	STMicroelectronics
TSA	Philips Semiconductor
TSH	STMicroelectronics TEMiC
U	Zentrurn Mikroelektronik Dresden Telefunken
UA	Philips Semiconductor Motorola Texas Instruments
UAA	Motorola Telefunken
UAF	Burr-Brown
UC	Unitrode Motorola STMicroetectronics
LJCC	Unitrode
UCN	Atlegro Microsystems
UD	Zentrum Mikroelektronik Dresden
UDN	Allegro Microsystems
DDK	Allegro Microsvstems
UGN	Altegro Microsvstems
ULN	STMicroetectronics Motorola Texas Instruments USMikroChips Allegro Microsystems
UM	Unitea Microelectronics (UMC)
UMA	Philips Sfemiconductor
UMC	United Microelectronics (UMC'
UPC	NEC
UPD	NEC
VGA	Burr-Brown
VPC	Burr-Brown
W	IC Works
WD	Western Digital
X	Xicor
XC	Motorola
XR	Exar
XTR	Burr-Brown
Z	Ziloq
ZH	Zetex Semiconducto's
ZLDO	Zetex Semiconductors
ZM	Zetex Semiconductors
ZMR	Zetex Semiconductors
ZN	GEC Plessev
ZR	Zetex Semiconductors
ZRA	Zetex Semiconductors
ZRB	Zetex Semiconductors
ZREF	Zetex Semiconductors
ZRT	Zetex Semiconductors
ZSD	Zetex Semiconductors
ZSM	Zetex Semiconductors

ЛОГОТИПЫ ФИРМ-ПРОИЗВОДИТЕЛЕЙ ЭЛЕКТРОННЫХ КОМПОНЕНТОВ

	8x8
	Acer
	Acer Laboratories
	Actel
	Advanced Analogic Technology
	Advanced Communication Devices (ACD)
	Advanced Hardware Architectures
	Advanced Hardware Architectures
	Advanced Linear Devices
	Advanced Micro Devices (AMD)
	Advanced Micro Systems
	Advanced Monolithic Systems
	Advanced Power Technology
	Aeroflex
	Agilent Technologies
	Aimtron Technology
	AlTech International
	AKM Semiconductor
	Alesis Semiconductor
	Aitima Communications
	Allayer Communications
	Allegro Microsystems
	Alliance
	Alpha Industries
	Alpha Microelectronics
	Alpha Semiconductor
	Altera
	American Microsystems
	American Microsystems
	AMI Semiconductor
	ANADIGICs
	Analog Devices
	Analog Devices
	Analog Integrations Corporation
	Analog Microelectronics
	Analog Systems
	Anchor Chips
	Apex Microtechnology
	Apex Microtechnology
	ARK Logic
	Arizona Microtek
	Astec Semiconductor
	ATAN Technology
	ATecoM

	ATI Technologies
	Atmel
	AT&T
	Auctor
	AudioCodes
	Aura Vision
	Aureal
	Austin Semiconductor
	Avance Logic
	Averlogic
	Bel Fuse
	Benchmarq Microelectronics
	BI Technologies
	Brooktree (see Rockwell)
	Burr Brown
	California Micro Devices
	Cambridge Silicon Radio
	Calogic
	Catalyst Semiconductor
	Catalyst Semiconductor
	C-Cube Microsystems
	Centon Electronics
	Century Microelectronics

	Cherry Semiconductor
	Chips and Technologies (see Intel)
	Chipcon AS
	Chrontel
	Cirrus Logic
	Clear Logic
	C-Media Electronics
	Collmer Semiconductor
	ComCore Semiconductor
	Conexant
	Consumer Microcircuits
	Cosmo Electronics
	Crystal (Cirrus Logic)
	C&S Technology
	Cygnal Integrated Products
	Cypress Semiconductor
	Cypress Semiconductor
	Cyrix Corporation
	Daewoo Semiconductor
	Dallas Semiconductor
	Dallas Semiconductor
	Dallas Semiconductor
	Data Delay Devices

	Datapath Systems
	Davicom Semiconductor
	Dense-Pac
	Diamond Technologies
	Dionics
	Diotec
	DTC Data Technology
	DTC Data Technology
	DVDO
	Dynex Semiconductor
	Electronic Devices (EDI)
	Elantec
	Elantec
	Electronic Designs (White Electronic Designs)
	Electronic Technology
	EG&G
	Enhanced Memory Systems
	Ensoniq Corp
	Ericsson
	ESS Technology
	Exar
	Exel Microelectronics (Rohm)
	Fagor Electronica
	Fairchild Semiconductor
	Fairchild Semiconductor
	Fuji Electric
	Fuji Electric
	Fujitsu
	Fujitsu
	Galileo Technology
	Galvantech
	GEC Plessey
	General Electric (Harris)
	General Instrument (General Semiconductor)
	General Instrument (General Semiconductor)
	General Instrument (General Semiconductor)
	General Semiconductor
	Genesys Logic
	Gennum
	GHZ Technology
	G-Link Technology
	Globespan Semiconductor
	Goodark
	Gould (see AMI)
	Harris (now Intersil)
	Harris (now Intersil)

Hewlett Packard - see Agilent Technologies
HFO
hi/fn
Hitachi
Holtek Microelectronics
Hualon Microelectronics
Hyundai
Hyundai
Hutson Industries
iC Designs — now Cypress
iC-Haus
iC-Haus
I-Cube
IC Works
IGS Technologies
IMP
Impala Linear
Infineon Technologies
Infineon Technologies
Infinite Technology
Information Storage Devices
Inmos (STMicroelectronics)
Integrated Circuit Designs
Integrated Circuit Solution
Integrated Circuit Systems
Integrated Circuit Systems
Integrated Device Technology (IDT)
Integrated Device Technology (IDT)
Integrated Logic Systems
Integrated Silicon Solutions
Integrated Technology Express
Integrated Telecom Express
Intel
Intel
InterFET
International Microcircuits
International Rectifier
Intersil
Intersil
Intersil
Intersil
ITT (Micronas Semiconductor)
IXYS
Korea Electronics (KEC)
KOTA Microcircuits
Lansdale Semiconductor

	Lansdale Semiconductor
	Lattice Semiconductor
	Lattice Semiconductor
	Lattice Semiconductor
	Legerity
	Level One Communications
	LG Semicon
	Linear Technology
	Linfinity Microelectronics
	Lite-On
	LSI Logic
	Lucent Technologies
	Macronix International
	Macronix International
	Marvell Semiconductor
	Matra MHS
	Matra MHS
	Matra MHS
	Matsushita Panasonic
	Matsushita Panasonic
	Maxim
	Media Vision
	Media Vision

	Micrel Semiconductor
	Micro Electronics
	Mikroelektronik Erfurt (DDR)
	Microchip Technology
	Micro Linear
	Microsemi
	Micron Technology
	Micronas
	Micronix Integrated Systems
	MicroPower Direct
	Microtune
	Mini-Circuits
	Mitel Semiconductor
	Mitsubishi
	MMC Networks
	Monolithic Memories (see Vantis)
	Mosaic Semiconductor
	Mosaid Systems
	Mosel Vitelec
	MDS Technologies
	MoSys
	Motorola
	Motorola

	M-Systems
	Murata
	Myson Technology
	mwave (by IBM)
	Naina Semiconductor
	Naina Semiconductor
	Naina Semiconductor
	Naina Semiconductor
	Naina Semiconductor
	NEC
	NEC
	New Japan Radio (NJR)
	Nippon Precision Circuits
	O2Micro
	Oak Technology
	OKI Semiconductor
	OKI Semiconductor
	OKI Semiconductor
	Omnirel
	Opti
	Orbit Semiconductor
	Oren Semiconductor
	Peregrine Semiconductor

	Performance Semiconductor
	Pericom Semiconductor
	PhaseLink Laboratories
	Philips Semiconductor
	PLX Technology
	PMC-Sierra
	Power Integrations
	PowerSmart
	PrairieComm
	Princeton Technology
	Precision Monolithics (Analog Devices)
	Protek Devices
	QLogic
	QT Optoelectronics
	Qualcomm
	QuickLogic
	Quality Semiconductor
	Rabbit Semiconductor
	Ramtron
	Raytheon Semiconductor
	Realtek Semiconductor
	Rectron
	Reliance - see Serverworks

	Rendition
	RCA Solid State (вошла в Harris)
	RF Micro Devices
	RICOH Semiconductor
	Rockwell
	Rohm
	S3
	Sage
	Sames
	Samsung Electronics
	Samsung Semiconductor
	Sanken
	Sanken
	Sanyo
	Sanyo
	Scenix Semiconductor
	SEEQ Technology
	Semikron International
	Semitron
	Seiko Epson Corp.
	Seiko Epson Corp.
	Seiko Instruments
	Semelab (Magnatec)
	Semicoa Semiconductors
	Semiconductor Technology
	Semtech
	Sescosem (STMicroelectronics)
	Sescosem (STMicroelectronics)
	SGS-Ates (STMicroelectronics)
	SGS-Ates (STMicroelectronics)
	Sharp
	Shindengen
	Siemens (now Infineon)
	Siemens (now Infineon)
	Sierra (now PMS-Sierra)
	Sigma Tel
	Signal Processing Technologies
	Signetics (now Philips)
	Space Bridge Semiconductor
	Silicon General - see Microcemi
	Siliconians
	Silicon Integrated Systems
	Siliconix
	Silicon Magic
	Silicon Storage Technology
	Silicon Systems (Texas Instruments)

	Silver Telecom
	Simtek Corporation
	Sipex
	SMC
	Solid State Optronics
	Solid State Scientific (Thomson-CSF)
	Sony
	Space Electronics
	Spectek
	Standard Microsystems
	Standard Microsystems
	Stanford Microdevices
	STMicroelectronics
	Stream Machine
	Summit Microelectronics
	Synergy Semiconductor (Micrel)
	Synertek
	Taiwan Memory Technology
	Taiwan Semiconductor
	TDK Semiconductor
	Teccor Electronics
	Teccor Electronics
	TelCom Semiconductor
	Teledyne (TelCom Semiconductor)
	Telefunken (вошла в Vishay)
	Teltone
	Tesla
	Texas Instruments
	Texas Instruments
	Thaler Corporation
	Thomson-CSF - see Atmel
	Toko America
	Torex Semiconductor
	Toshiba
	Toshiba
	Toshiba
	Trident
	TriQuint Semiconductor
	Triscend
	Tseng Labs
	Tundra
	Tvia Technology
	Ubicom (formerly Scenix)
	United Microelectronics Corp (UMC)
	United Technologies Microelectronics Center
	Unitrode - see TI

USAR	USAR Systems
USAR	USAR Systems
	Utron Technology
	V3 Semiconductor
	Vadem
	Vanguard International Semiconductor
	Vantis
	Via Technologies
Virata	Virata
VISHAY	Vishay Intertechnology
	Vision Tech
	Vitelic
	Vitesse Semiconductor
	VLSI Technology
	Volterra
	VTC
	Waferscale Integration
WEITEK	Weitek (Rockwell)
WDC	Western Design Center
WDC	Western Digital
	Western Digital
	White Electronic Designs
Winbond	Winbond
	Wolfsom Microelectronics
	Xemics
Xicor	Xicor
	Xicor
XILINX	Xilinx
	Yamaha
	Zarlink Semiconductor (form. Mitel)
	Zetex Semiconductors
	ZF Microsystems
	Zilog
Zilog	Zilog
	Zilog
	Zilog
	Zentrum Mikroelektronik
	Zoran Corporation
	Zucotto Wireless